
RCA Linear Integrated Circuits and MOS/FET's

This DATABOOK contains detailed technical information on the full line of linear integrated circuits and the low-power line of metal-oxide-semiconductor field-effect transistors (MOS/FET's) currently available from RCA Solid State Division. This broad spectrum of products include many highly diverse types intended for a wide range of circuit functions in industrial and/or consumer applications.

The first section, a general over-all guide to available products, contains a complete index of types, photographs of the wide variety of package options, product classification and selection guides, recommended operating and handling procedures, a list of special terms and symbols, and a cross-reference listing that shows the recommended RCA replacement types for many popular industry devices. This general section is followed by technical data on individual types grouped into eleven broad product categories, including: Operational Amplifiers, Voltage Comparators, Data-Conversion Circuits, Arrays, Power Control Circuits, Differential Amplifiers, Special-Function Circuits, TV/CATV Circuits, Audio Circuits, Radio Circuits, and MOS/FET's. The first page of each data section lists all the types included in the section grouped according to specific circuit functions together with a reference to the page that contains the technical data for each type.

The final section of the DATABOOK lists high-reliability types supplied for military, aerospace, and critical industrial applications and defines the screening levels to which each of them are supplied, shows dimensional outlines for all package types, and lists, together with a brief abstract, current RCA application notes on linear integrated circuits and MOS/FET's.

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The device data shown for some types are indicated as preliminary. **Preliminary data** are intended for guidance purposes in evaluating devices for equipment design. Such data are shown for types currently being designed for inclusion in our standard line of commercially available products. For current information on the status of preliminary programs, please contact your local RCA sales office.

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Linear Integrated Circuits

Index to Devices

Type Number	Package Suffix						Data Bulletin File No.	Page
	T	S	E*		H	—		
CA080	T	S	E*		H	—	1238	83
CA081	T	S	E*		H	—	1238	83
CA082	T	S	E*		H	—	1238	83
CA083	—	—	—	E1§	H	—	1238	83
CA084	—	—	—	E1§	H	—	1238	83
CA101	T	S	—	—	—	—	786	28
CA124	E	—	—	—	—	—	796	104
CA139	E	—	—	—	—	—	795	301
CA139A	E	—	—	—	—	—	795	301
CA158	T	S	E	—	—	—	1019	93
CA158A	T	S	E	—	—	—	1019	93
CA201	T	S	—	—	—	—	786	28
CA224	E	—	—	—	—	—	796	104
CA239	E	—	—	—	—	—	795	301
CA239A	E	—	—	—	—	—	795	301
CA258	T	S	E	—	—	—	1019	93
CA258A	T	S	E	—	—	—	1019	93
CA270	W	—	—	—	—	—	897E	871
CA301A	T	S	E	—	H	—	786	28
CA307	T	S	E	—	H	—	785	34
CA311	T	S	E	—	—	—	797	270
CA324	E	—	H	—	—	—	796	104
CA339	E	—	H	—	—	—	795	301
CA339A	E	—	—	—	—	—	795	301
CA358	T	S	E	H	—	—	1019	93
CA358A	T	S	E	—	—	—	1019	93
CA555	T	S	E	—	—	—	834	653
CA555C	T	S	E	—	H	—	834	653
CA723	T	E	—	—	—	—	788	520
CA723C	T	E	H	—	—	—	788	520
CA741	T	S	E	—	—	—	531	38
CA741C	T	S	E	—	H	—	531	38
CA747	T	E	—	—	—	—	531	38
CA747C	T	E	—	H	—	—	531	38
CA748	T	S	E	—	—	—	531	38
CA748C	T	S	E	—	H	—	531	38
CA758	E	—	—	—	—	—	760	38
CA920A	E	—	—	—	—	—	1132	771
CA1190	Q	—	—	—	—	—	1134	924
CA1191	E	—	—	—	—	—	1347	928
CA1310A	E	—	—	—	—	—	1254	855
CA1352	E	—	—	—	—	—	961	876
CA1391	E	—	—	—	—	—	981	775
CA1394	E	—	—	—	—	—	981	775
CA1398	E	—	—	—	—	—	686	673
CA1458	T	S	E	—	H	—	531	38
CA1524	E	—	—	—	H	—	1239	528
CA1558	T	S	E	—	—	—	531	38
CA1724	E	—	—	—	—	—	1228	393
CA1725	E	—	—	—	H	—	1228	393
CA2002	*	M	—	—	—	—	1156	1004
CA2004	*	M	—	—	—	—	1105	1009
CA2111A	E	Q	—	—	—	—	612	932
CA2136A	E	—	—	—	—	—	1262	937
CA2524	E	—	—	—	H	—	1239	528
CA2904	T	E	—	—	—	—	1019	93
CA3000	■	H	—	—	—	—	121	562
CA3001	■	H	—	—	—	—	122	569
CA3002	■	H	—	—	—	—	123	612
CA3004	■	H	—	—	—	—	124	575
CA3005	■	H	—	—	—	—	125	581
CA3006	■	—	—	—	—	—	125	581
CA3007	■	—	—	—	—	—	126	588
CA3008	■	—	—	—	—	—	316	114
CA3008A	■	—	—	—	—	—	310	121
CA3010	■	—	—	—	—	—	316	114
CA3010A	■	—	—	—	—	—	310	121
CA3011	■	H	—	—	—	—	128	939
CA3012	■	—	—	—	—	—	128	939
CA3013	■	—	—	—	—	—	129	945
CA3014	■	—	—	—	—	—	129	945
CA3015	■	—	H	—	—	—	316	114
CA3015A	■	—	—	—	—	—	310	121

Type Number	Package Suffix						Data Bulletin File No.	Page
	■	■	■	■	■	■		
CA3016	■	■	—	—	—	—	316	114
CA3016A	■	■	—	—	—	—	310	121
CA3018	■	—	H	—	—	—	338	396
CA3018A	■	—	—	—	—	—	338	396
CA3019	■	H	—	—	—	—	236	384
CA3020	■	H	—	—	—	—	339	500
CA3020A	■	—	—	—	—	—	339	500
CA3021	■	—	—	—	—	—	243	129
CA3022	■	—	—	—	—	—	243	129
CA2023	■	H	—	—	—	—	243	129
CA3026	■	H	—	—	—	—	338	354
CA3028A	■	S	—	—	H	—	382	593
CA3028B	■	S	—	—	—	—	382	593
CA3029	●	—	—	—	—	—	316	114
CA3029A	●	—	—	—	—	—	310	121
CA3030	●	—	—	—	—	—	316	114
CA3030A	●	—	—	—	—	—	310	121
CA3035	■	VI	H	—	—	—	274	362
CA3036	■	—	—	—	—	—	275	402
CA3037	†	—	—	—	—	—	316	114
CA3037A	†	—	—	—	—	—	310	121
CA3038	†	—	—	—	—	—	316	114
CA3038A	†	—	—	—	—	—	310	121
CA3039	■	—	H	—	—	—	343	386
CA3040	■	—	—	—	—	—	363	604
CA3041	Δ	—	—	—	—	—	318	952
CA3042	Δ	—	—	—	—	—	319	960
CA3045	†	F	—	H	—	—	341	404
CA3046	●	—	—	—	—	—	341	404
CA3048	●	H	—	—	—	—	377	365
CA3049	T	—	H	—	—	—	611	372
CA3050	†	—	—	—	—	—	361	410
CA3051	●	—	—	—	—	—	361	410
CA3052	●	—	—	—	—	—	387	377
CA3053	■	S	—	—	—	—	382	593
CA3054	●	—	H	—	—	—	388	354
CA3058	†	—	—	—	—	—	490	550
CA3059	●	H	—	—	—	—	490	550
CA3060	D	E	H	—	—	—	537	224
CA3060A	D	—	—	—	—	—	537	224
CA3060B	D	—	—	—	—	—	537	224
CA3064	E	—	—	—	—	—	396	660
CA3065	Δ	—	—	—	—	—	412	968
CA3068	Δ	—	—	—	—	—	467	880
CA3070	●	—	—	—	—	—	468	678
CA3071	●	—	—	—	—	—	468	678
CA3072	●	—	—	—	—	—	468	678
CA3075	Δ	H	—	—	—	—	429	1014
CA3076	■	H	—	—	—	—	430	1018
CA3078	T	S	E	H	—	—	535	237
CA3078A	T	S	E	H	—	—	535	237
CA3079	●	—	—	—	—	—	490	550
CA3080	■	E	S	H	—	—	475	245
CA3080A	■	E	S	H	—	—	475	245
CA3081	●	F	H	—	—	—	480	332
CA3082	●	F	H	—	—	—	480	332
CA3083	●	F	—	H	—	—	481	418
CA3084	●	—	H	—	—	—	482	422
CA3085	■	E	S	—	H	—	491	543
CA3085A	■	S	E	—	—	—	491	543
CA3085B	■	S	—	—	—	—	491	543
CA3086	●	F	—	—	—	—	483	427
CA3088	E	—	—	—	—	—	560	1022
CA3089	E	—	—	—	—	—	561	1026
CA3090A	Q	—	—	—	—	—	684	860
CA3091	D	E	H	—	—	—	534	618
CA3093	E	H	—	—	—	—	533	432
CA3094	T	S	E	H	—	—	598	213
CA3094A	T	S	E	—	—	—	598	213
CA3094B	T	S	—	—	—	—	598	213
CA3096	E	H	—	—	—	—	595	438
CA3096A	E	—	—	—	—	—	595	438
CA3096C	E	—	—	—	—	—	595	438

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CA3097	E	H	—	—	—	—	633	448
CA3098	T	S	E	H	—	—	896	278
CA3099	E	H	—	—	—	—	620	285
CA3100	T	S	E	H	—	—	625	135
CA3102	E	H	—	—	—	—	611	372
CA3105	*	M	—	—	—	—	1382	46
CA3118	T	H	—	—	—	—	532	459
CA3118A	T	—	—	—	—	—	532	459
CA3120	E	—	—	—	—	—	907	819
CA3121	E	—	—	—	—	—	688	693
CA3123	E	—	—	—	—	—	631	1032
CA3125	E	—	—	—	—	—	685	699
CA3126	Q	E	—	—	—	—	860	702
CA3127	E	—	—	—	—	—	662	466
CA3128	Q	T	—	—	—	—	1161	471
CA3130	T	S	E	H	—	—	817	141
CA3130A	T	S	E	—	—	—	817	141
CA3130B	T	S	E	—	—	—	817	141
CA3134	—	EM	QM	—	—	—	1097	974
CA3135	E	—	—	—	—	—	1021	827
CA3136	E	—	—	—	—	—	1158	887
CA3137	E	—	—	—	—	—	970	709
CA3138	E	H	—	—	—	—	1131	473
CA3138A	E	—	—	—	—	—	1131	473
CA3139	E	Q	—	—	—	—	905	668
CA3140	T	S	E	H	—	—	957	156
CA3140A	T	S	E	—	—	—	957	156
CA3140B	T	S	—	—	—	—	957	156
CA3141	E	—	—	—	—	—	906	390
CA3142	E	—	—	—	—	—	907	819
CA3143	E	—	—	—	—	—	1138	834
CA3144	E	—	—	—	—	—	1137	839
CA3145	E	—	—	—	—	—	1175	714
CA3146	E	H	—	—	—	—	532	459
CA3146A	E	—	—	—	—	—	532	459
CA3151	E	—	—	—	—	—	1160	721
CA3152	E	—	—	—	—	—	1351	48
CA3153	E	—	—	—	—	—	1142	892
CA3154	E	—	—	—	—	—	1183	780
CA3156	E	—	—	—	—	—	1265	844
CA3157	E	—	—	—	—	—	1184	786
CA3158	E	—	—	—	—	—	1170	725
CA3159	E	—	—	—	—	—	1136	792
CA3160	T	S	E	H	—	—	976	176
CA3160A	T	S	E	—	—	—	976	176
CA3160B	T	S	—	—	—	—	976	176
CA3161	E	—	—	—	—	—	1079	335
CA3162	E	—	—	—	—	—	1080	308
CA3163	E	—	—	—	—	—	1092	980
CA3164	E	—	—	—	—	—	1139	647
CA3165	E	E1§	—	—	—	—	1278	494
CA3166	E	—	—	—	—	—	1100	984
CA3168	E	—	—	—	—	—	1140	339
CA3169	*	M	—	—	—	—	1277	508
CA3170	E	—	—	—	—	—	1129	730
CA3172	E	—	—	—	—	—	1130	737
CA3179	E	—	—	—	H	—	1176	630

Type Number	Package Suffix						Data Bulletin File No.	Page
CA3183	E	H	—	—	—	—	532	459
CA3183A	E	—	—	—	—	—	532	459
CA3189	E	—	—	—	—	—	1046	1036
CA3190	E	—	—	—	—	—	1204	796
CA3191	E	—	—	—	—	—	1268	899
CA3192	E	—	—	—	—	—	1304	912
CA3193	T	S	E	H	—	—	1249	52
CA3193A	T	S	E	H	—	—	1249	52
CA3193B	T	S	E	H	—	—	1249	52
CA3194	E	—	—	—	—	—	1270	740
CA3195	E	—	—	—	—	—	1260	866
CA3199	E	—	—	—	—	—	1302	639
CA3201	E	—	—	—	—	—	1346	748
CA3202	E	—	—	—	—	—	1348	802
CA3207	E	H	—	—	—	—	1322	343
CA3208	E	H	—	—	—	—	1322	343
CA3209	E	—	—	—	—	—	1343	1042
CA3210	E	—	—	—	—	—	1361	809
CA3211	E	—	—	—	—	—	1379	644
CA3215	E	—	—	—	—	—	1358	990
CA3216	E	—	—	—	—	—	1362	993
CA3217	E	—	—	—	—	—	1332	756
CA3219	E	—	—	—	—	—	1359	514
CA3221	E	—	—	—	—	—	1057	765
CA3223	E	—	—	—	—	—	1361	809
CA3227	E	—	—	—	—	—	1345	476
CA3228	E	—	—	—	—	—	—	517
CA3240	E*	E1§	—	—	—	—	1050	193
CA3240A	E*	E1§	—	—	—	—	1050	193
CA3246	E	—	—	—	—	—	1345	476
CA3260	T	S	E	H	—	—	1266	208
CA3260A	T	S	E	H	—	—	1266	208
CA3260B	T	S	E	H	—	—	1266	208
CA3280	E	—	—	—	—	H	1174	260
CA3280A	E	—	—	—	—	H	1174	260
CA3290	T	S	E*	E1§	—	—	1049	291
CA3290A	T	S	E*	E1§	—	—	1049	291
CA3290B	T	S	—	—	—	—	1049	291
CA3300	D	H	—	—	—	—	1316	316
CA3308	D	—	—	—	—	—	1352	327
CA3401	E	—	H	—	—	—	630	110
CA3420	S	T	E	H	—	—	1320	63
CA3420A	S	T	E	H	—	—	1320	63
CA3420B	S	T	E	H	—	—	1320	63
CA3440	S	T	E	H	—	—	1318	254
CA3440A	S	T	E	H	—	—	1318	254
CA3440B	S	T	E	H	—	—	1318	254
CA3493	S	T	E	—	—	—	1290	68
CA3493A	S	T	E	—	—	—	1290	68
CA3493B	S	T	E	—	—	—	1290	68
CA3524	E	—	—	—	—	H	1239	528
CA3600	E	—	—	—	—	—	619	479
CA6078A	T	S	—	—	—	—	592	79
CA6741	T	S	—	—	—	—	592	79
CA7607	E	—	—	—	—	—	1350	920
CA7611	E	—	—	—	—	—	1350	920
CD3226	E	—	—	—	—	—	1365	997

- No designated suffix letter for this type in TO-5 style package
- ‡ No designated suffix letter for this type of ceramic flat package
- No designated suffix letter for this type in dual-in-line plastic package
- † No designated suffix letter for this type in dual-in-line ceramic package

- △ No designated suffix letter for this type in quad-in-line plastic package
- * In 8-lead dual-in-line Mini-DIP package
- § In 14-lead dual-in-line plastic package
- * No designated suffix letter for this type in TO-220-style package with vertical-mount lead form.

Linear Integrated Circuits

Packages

RCA linear device packages are identified by letters as indicated in the following chart. When ordering a

linear device, it is important that the appropriate suffix letter(s) be affixed to the type number of the device.

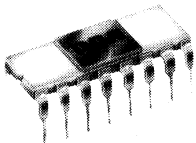
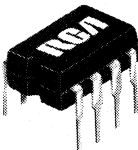
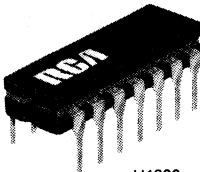
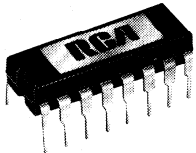
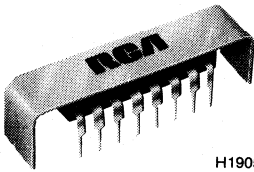
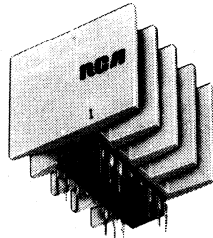
Package	Suffix Letter
Dual-In-Line Welded-Seal Ceramic Package	D
Dual-In-Line Plastic Package	E
Dual-In-Line Frit-Seal Ceramic Package	F
Chip	H
Dual-In-Line Plastic Package with "Power Slab"	P
Modified Dual-In-Line Plastic Package with "Power Slab"	EM
Modified Quad-In-Line Plastic Package	QM
Quad-In-Line Plastic Package	Q
TO-5 Style Package with Dual-In-Line Formed Leads (DIL-CAN)	S
TO-5 Style Package with Straight Leads	T
TO-220 Style Package with Horizontal-Mount Lead Form	M
TO-5 Style Package with Radial Formed Leads	V1
Staggered Quad-In-Line Plastic Package	W
Ceramic Flat Package	K

Notes:

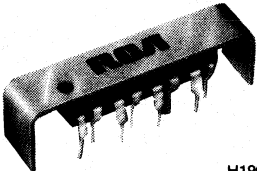
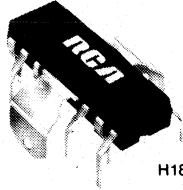
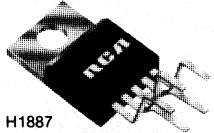
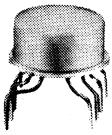
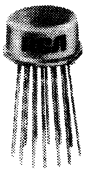

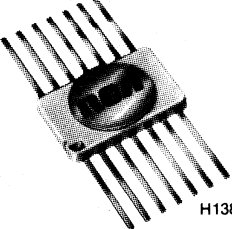
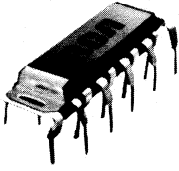
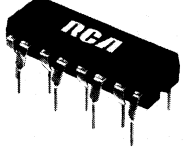
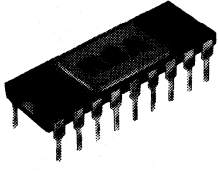

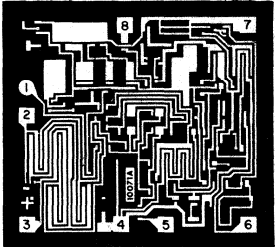
1. Some types may have an additional "M" suffix following the package designation suffix, i.e., CA3134EM. The additional "M" suffix simply indicates that the device is a mechanical variant of the basic package type.

2. RCA linear integrated circuits are provided in chip form to allow customer design of special and complex

circuits to suit individual needs. Linear chips are electrically identical to and offer the features of their counterparts, sealed in ceramic, TO-5, and plastic packages. The package-options charts shown with the functional diagrams for each generic type of RCA linear integrated circuit indicate those types for which chip versions are available.

<p>D Suffix Dual-In-Line Welded-Seal Ceramic Package</p>  <p>H1844</p> <p>14 and 16-lead versions</p>	<p>E Suffix Dual-In-Line Plastic Package</p>  <p>H1817</p> <p>8, 14, 16, 18, 22, 24 and 28-lead versions</p>	<p>F Suffix Dual-In-Line Frit-Seal Ceramic Package</p>  <p>H1806</p> <p>14 and 16-lead versions</p>
<p>P Suffix "Power Slab" Plastic Dual-In-Line Package</p>  <p>H1902</p> <p>CA3136P only</p>	<p>EM Suffix Modified 16-lead Dual-In-Line Plastic Package with "Power Slab"</p>  <p>H1905</p> <p>CA3134EM only</p>	<p>EM Suffix Modified 16-lead Dual-In-Line Plastic Package with "Power Slab"</p>  <p>H1827</p>

Packages (Cont'd)

<p>QM Suffix Quad-In-Line Plastic Package (QUIP) with "Power Slab"</p>  <p>H1906</p> <p>16-lead version</p>	<p>Q Suffix Modified 16-lead QUIP</p>  <p>H1825</p>	<p>VERSA-V and VERSA-V1 TO-220 Style Plastic Package with Vertical-Mount Lead Form</p>  <p>H1887</p> <p>(Versions with horizontal-mount lead form are also available).</p>
<p>S Suffix TO-5 Style Package with Dual-In-Line Formed Leads (DIL-CAN)</p>  <p>H1787</p> <p>8-lead version</p>	<p>T Suffix TO-5 Style Package with Straight Leads</p>  <p>H1463</p> <p>8, 10, and 12-lead versions</p>	<p>V1 Suffix TO-5 Style Package with Radial Formed Leads</p>  <p>H1561</p> <p>8, 10, and 12-lead versions</p>
<p>K Suffix Ceramic Flat Package</p>  <p>H1383R1</p> <p>14-lead version</p>	<p>Shielded 20-lead Quad-In-Line Plastic Package</p>  <p>H1704</p>	<p>W Suffix Staggered Quad-In-Line Plastic Package</p>  <p>H1885</p> <p>14 and 16-lead versions</p>
<p>D Suffix 18-lead Dual-In-Line Side-Brazed Ceramic Package</p>  <p>H1910</p>	<p>JEDEC TO-72</p>  <p>H1299</p>	<p>H Suffix Chip</p>  <p>92CM-32235</p>

Linear Integrated Circuits

Product Classification Chart

Industrial Circuits							
OPERATIONAL AMPLIFIERS				DIFFERENTIAL AMPLIFIERS		ARRAYS	
General Purpose		General Purpose Wideband	Variable			Amplifier/ Diode	Transistor
Single Unit	Dual Unit	Single Unit	High Current	CA3000	Amplifier	CA1724	CA3096
CA101	CA082*	CA080*	CA3094	CA3001	CA3026	CA1725	CA3097
CA201	CA083*	CA081*	Micropower	CA3004	CA3035	CA3018	CA3118
CA301A	CA158	CA3008	CA3060	CA3005	CA3048	CA3036	CA3127
CA307	CA258	CA3010	CA3078	CA3006	CA3049	CA3045	CA3128
CA741	CA358	CA3015	CA3080	CA3007	CA3052	CA3046	CA3138
CA748	CA747	CA3016	CA3440*	CA3026	CA3054	CA3050	CA3146
CA3105	CA1458	CA3029	CA6078A*	CA3028	CA3060	CA3051	CA3183
CA3152*	CA1558	CA3030	Dual Unit	CA3040	CA3102	CA3081	CA3227
CA3193*	CA2904	CA3037	CA3280	CA3049		CA3082	CA3246
CA3420*	Quad Unit	CA3038		CA3050	Diode	CA3083	▲CA3600
CA3493*	CA084*	CA3100*		CA3051	CA3019	CA3084	
CA6741*	CA124	CA3130*		CA3053	CA3039	CA3086	
	CA224	CA3140*		CA3054	CA3141	CA3093	
	CA324	CA3160*		CA3102			
	CA3401	Dual Unit					
		CA3240*					
		CA3260*					
POWER CONTROL CIRCUITS		DATA CONVERSION		SPECIAL FUNCTION CIRCUITS			
Voltage Regulators	Solenoid & Motor Drivers	A/D Converters		Timer	Automotive Circuits	Broadband (Video) Amplifiers	
CA723	CA3169	CA3162		CA555	CA3105	CA080*	
CA1524	CA3219	CA3300		Four Quadrant Multiplier	CA3130*	CA082*	
CA2524		CA3308		CA3091	CA3160*	CA083*	
CA3085	Power Amplifiers	Display Drivers		Single-Chip Detector Alarm	CA3161	CA084*	
CA3524	CA3020	CA3161 CA3081		Systems	CA3165	CA3001	
Zero-Voltage Switches	CA3105	CA3168 CA3082		CA3164*	CA3168	CA3002	
CA3058	Automotive Ignition Switch	CA3207*		Prescalers	CA3169	CA3021	
CA3059	CA3165	CA3208*		CA3179	CA3207*	CA3022	
CA3079		VOLTAGE COMPARATORS		CA3199	CA3208*	CA3023	
Programmable Schmitt Triggers	Universal Controller	Single Unit		CA3211	CA3219	CA3024	
CA3098	CA3228	CA311			CA3228	CA3025	
CA3099		CA3098+			CA3260*	CA3026	
		CA3099+			CA3290*	CA3027	
		Dual Unit				CA3028	
		CA3290*				CA3029	
		Quad Unit				CA3030	
		CA139				CA3031	
		CA239				CA3032	
		CA339				CA3033	
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						CA3221	

Product Classification Chart

Consumer Circuits					
TV/CATV CIRCUITS			AUDIO CIRCUITS	RADIO CIRCUITS	
AFT CA3064 CA3139	Horizontal/ Vertical Systems	PIX IF CA270 CA1352	Drivers CA3094	AM/FM Com- munications Circuits	FM IF Circuits Gain Blocks
Chroma Systems CA1398 CA3070 CA3071 CA3072 CA3121 CA3126 CA3128** CA3137 CA3145 CA3151 CA3158 CA3170 CA3172 CA3194** CA3201 CA3217 CA3221	CA920A CA1391 CA1394 CA3154 CA3159 CA3190*** CA3202 CA3210 CA3223*** Sync/AGC Circuits CA3120 CA3142 Luminance Processors CA3135 CA3143 CA3144 CA3156 Multiplex Decoders CA758 CA1310A CA3090A CA3195	CA3068 CA3136 CA3153 CA3191 CA3192 CA7607 CA7611 Remote Control CA3035 Sound IF CA1190 CA1191 CA2111A CA2136A CA3011 CA3012 CA3013 CA3014 CA3041 CA3042 CA3065 CA3134 Tuning CA3140 CA3152 * CA3163 CA3166 CA3168 CA3199 CA3211 Videodisc Circuits CA2111A CA3215 CA3216 CD3226▲	Power Amplifiers CA2002 CA2004 Preamplifiers CA3036 CA3048 CA3052	CA2111A CA2136A CA3011 CA3012 CA3013 CA3014 CA3043 CA3075 CA3076 CA3088 CA3089 CA3123 CA3143 CA3179 CA3189 CA3199 CA3209	CA3011 CA3012 CA3076 Subsystems CA2111A CA2136A CA3013 CA3014 CA3075 CA3089 CA3189 CA3209
			MOS/FET's		
			Single Gate	Dual Gate	Dual Gate Protected
			3N128	3N140	3N187
			3N138	3N141	3N200
			3N139	3N159	3N204
			3N142	40600	3N205
			3N143	40601	3N206
			3N152	40602	3N211
			3N153	40603	3N212
			3N154	40604	3N213
			40467A		40673
			40468A		40819
			40559A		40820
					40821
					40822
					40823
					40841

▲ CMOS types **PAL ***625 Line *BiMOS types

Operating and Handling Considerations

Solid state devices are being designed into an increasing variety of electronic equipment because of their high standards of reliability and performance. However, it is essential that equipment designers be mindful of good engineering practices in the use of these devices to achieve the desired performance.

This Note summarizes important operating recommendations and precautions which should be followed in the interest of maintaining the high standards of performance of linear integrated circuits and MOS field-effect transistors.

The ratings included in RCA data bulletins are based on the Absolute Maximum Rating System, which is defined by the following Industry Standard (JEDEC) statement:

Absolute-Maximum Ratings are limiting values of operating and environmental conditions applicable to any electron device of a specified type as defined by its published data, and should not be exceeded under the worst probable conditions.

The device manufacturer chooses these values to provide acceptable serviceability of the device, taking no responsibility for equipment variations, environmental variations, and the effects of changes in operating conditions due to variations in device characteristics.

The equipment manufacturer should design so that initially and throughout life no absolute-maximum value for the intended service is exceeded with any device under the worst probable operating conditions with respect to supply-voltage variation, equipment component variation, equipment control adjustment, load variation, signal variation, environmental conditions, and variations in device characteristics.

It is recommended that equipment manufacturers consult RCA whenever device applications involve unusual electrical, mechanical or environmental operating conditions.

GENERAL CONSIDERATIONS

The design flexibility provided by integrated circuits and MOS/FET's makes possible their use in a broad range of applications and under many different operating conditions. When incorporating these devices in equipment, designers should anticipate the rare possibility of device failure and make certain that no safety hazard would result from such an occurrence.

The small size of these devices provides obvious advantages to the designers of electronic equipment. However, it should be recognized that these compact devices usually provide only relatively small insulation area between adjacent leads and the metal envelope. When these devices are used in moist or contaminated atmospheres, therefore, supplemental protection must be provided to prevent the development of electrical conductive paths across the relatively small insulating surfaces.

Devices should not be connected into or disconnected from circuits with the power on because high transient voltages may cause permanent damage to the devices.

TESTING PRECAUTIONS

In common with many electronic components, solid-state devices should be operated and tested in circuits which have reasonable values of current limiting resistance, or other forms of effective current overload protection. Failure to observe these precautions can cause excessive internal heating of the device resulting in destruction and/or possible shattering of the enclosure.

MOUNTING

Integrated circuits are normally supplied with lead-tin plated leads to facilitate soldering into circuit boards. In those relatively few applications requiring welding of the device leads, rather than soldering, the devices may be obtained with gold or nickel plated Kovar leads.* It should be recognized that this type of plating will not provide complete protection against lead corrosion in the presence of high humidity and mechanical stress. The aluminum-foil-lined cardboard "sandwich pack" employed for static protection of the flat-pack also provides some additional protection against lead corrosion, and it is recommended that the devices be stored in this package until used.

When integrated circuits are welded onto printed circuit boards or equipment, the presence of moisture between the closely spaced terminals can result in conductive paths that may impair device performance in high-impedance applications. It is therefore recommended that conformal coatings or potting be provided as an added measure of protection against moisture penetration.

In any method of mounting integrated circuits which involves bending or forming of the device leads, it is extremely important that the lead be supported and clamped between the bend and the package seal, and that bending be done with care to avoid damage to lead plating. In no case should the radius of the bend be less than the diameter of the lead, or in the case of rectangular leads, such as those used in RCA 14-lead and 16-lead flat-packages, less than the lead thickness. It is also extremely important that the ends of the bent leads be straight to assure proper insertion through the holes in the printed-circuit board.

MOS FIELD-EFFECT TRANSISTORS

Insulated-Gate Metal Oxide-Semiconductor Field-Effect Transistors (MOS FETs), like bipolar high-frequency transistors, are susceptible to gate insulation damage by the electrostatic discharge of energy through the devices. Electrostatic discharges can occur in an MOS FET if a type with an unprotected gate is picked up and the static charge, built in the handler's body capacitance, is discharged through the device. With proper handling and applications procedures, however, MOS transistors are currently being extensively used in production by numerous equipment manufacturers in military, industrial, and consumer applica-

* MIL-38510A, paragraph 3.5.6.1(a), lead material.

Operating and Handling Considerations

tions, with virtually no problems of damage due to electrostatic discharge.

In some MOS FETs, diodes are electrically connected between each insulated gate and the transistor's source. These diodes offer protection against static discharge and in-circuit transients without the need for external shorting mechanisms. MOS FETs which do not include gate-protection diodes can be handled safely if the following basic precautions are taken:

1. Prior to assembly into a circuit, all leads should be kept shorted together either by the use of metal shorting springs attached to the device by the vendor, or by the insertion into conductive material such as "ECCOSORB* LD26" or equivalent.
(NOTE: Polystyrene *insulating* "SNOW" is not sufficiently conductive and should not be used.)
2. When devices are removed by hand from their carriers, the hand being used should be grounded by any suitable means, for example, with a metallic wristband.
3. Tips of soldering irons should be grounded.
4. Devices should never be inserted into or removed from circuits with power on.

*Trade Mark: Emerson and Cumming, Inc.

SOLID STATE CHIPS

Solid state chips, unlike packaged devices, are non-hermetic devices, normally fragile and small in physical size, and therefore, require special handling considerations as follows:

1. Chips must be stored under proper conditions to insure that they are not subjected to a moist and/or contaminated atmosphere that could alter their electrical, physical, or mechanical characteristics. After the shipping container is opened, the chip must be stored under the following conditions:
 - A. Storage temperature, 40°C max.
 - B. Relative humidity, 50% max.
 - C. Clean, dust-free environment.
2. The user must exercise proper care when handling chips to prevent even the slightest physical damage to the chip.
3. During mounting and lead bonding of chips the user must use proper assembly techniques to obtain proper electrical, thermal, and mechanical performance.
4. After the chip has been mounted and bonded, any necessary procedure must be followed by the user to insure that these non-hermetic chips are not subjected to moist or contaminated atmosphere which might cause the development of electrical conductive paths across the relatively small insulating surfaces. In addition, proper consideration must be given to the protection of these devices from other harmful environments which could conceivably adversely affect their proper performance.

Linear Integrated Circuits

Terms and Symbols

A	closed-loop voltage gain	I _A	amplifier supply current	I _{OM}	peak output current
A _{AF}	audio amplifier gain	I _{ABC}	amplifier bias current	I _{OM}	magnitude of peak output current
A _{DIFF}	differential voltage gain	I _{AGC}	AGC source current	I _{OM} ⁺	current
ACC	automatic chroma control	I _B	base current	I _{OM} ⁺	maximum output current (source)
AFC	automatic frequency control	I _C	collector current	I _{OM} ⁻	maximum output current (sink)
AFT	automatic fine tuning	I _{CBO}	collector cutoff current	I _p	photo current
AGC	automatic gain control	I _{CEO}	collector cutoff current	I _{p-p}	peak-to-peak output current
AMR	am rejection	I _{CE(OFF)}	output leakage current	I _Q	total quiescent current
A _{OL}	open-loop voltage gain	I _D	drain current	I _{QPL}	charge-pump input current
A _V	amplifier voltage gain	I _{D(ON)}	dc on-state drain current	I _R	dc reverse (leakage) current
b _{fs}	small-signal, common-source, forward transfer susceptance (imaginary part of corresponding admittance; see V _{fs})	I _{DARK}	dark current	I _{REFO}	supply current for reference supply voltage
b _{is}	small-signal, common-source, input susceptance (imaginary part of corresponding admittance; see y _{is})	I _{DF}	diode forward current	I _{SSO}	strobe load current voltage (V _{SS})
b _{os}	small-signal, common-source, output susceptance (imaginary part of corresponding admittance; see y _{os})	I _{DDO}	supply current for drain supply voltage (V _{DD})	I _{SXO}	supply current for supply voltage
b _{rs}	small-signal, common-source, reverse transfer susceptance (imaginary part of corresponding admittance; see V _{rs})	I _{DS}	zero-gate (bias) drain current (dual-gate types)	I _{TH}	threshold current
BW	bandwidth (unity gain)	I _{DSS}	zero-gate (bias) drain current (single-gate types)	I _{TOTAL}	total supply current
BW _{OL}	open-loop bandwidth	I _F	forward current	k _N	normalized factor (k _N = k/k _p)
C _{BI}	base-to-substrate capacitance	I _G	channel (input) gate lead current	MAG	maximum available power gain
C _{CB}	collector-to-base capacitance	I _{GR}	channel (input) gate reverse current	MUG	maximum useable power gain (unneutralized)
C _{EB}	emitter-to-base capacitance	I _{GS}	gate terminal current (single-gate types)	NF	noise factor
C _{EXT}	external capacitance	I _{G1S}	gate-No.1 terminal current dual-gate types	PO	power output
C _{FB}	feedback capacitance	I _{G2S}	gate-No. 2 terminal current dual-gate types	PD	device dissipation
C _I	input capacitance	I _{GSSF}	gate-to-source forward leakage current, all other terminals shorted to source (dual-gate types)	PSRR	power supply rejection ratio
C _{ios}	small-signal output capacitance	I _{G1SSF}	gate-No.1 source forward leakage current, all other terminals shorted to source (dual-gate types)	r _{ds(off)}	small-signal drain-to-source off-state resistance
C _{is}	small-signal, common-source short-circuit input capacitance	I _{G2SSF}	gate-No. 2-to-source forward leakage current, all other terminals shorted to source (dual-gate types)	r _{ds(on)}	static drain-to-source on-state resistance
C _{iss}	small-signal, common-source short-circuit input capacitance	I _{GSSR}	gate-to-source reverse leakage current, all other terminals shorted to source (single-gate types)	R _{GS}	gate leakage-current resistance
C _{I-O}	input-to-output capacitance; data in/out capacitance	I _{G1SSR}	gate-No. 1-to-source reverse leakage current, all other terminals shorted to source (dual-gate types)	R _O	output resistance
CMMR	common-mode rejection ratio	I _{G2SSR}	gate-No.2-to-source reverse leakage current, all other terminals shorted to source (dual-gate types)	R _o	low-frequency output resistance
C _O	output capacitance	I _{GSSR}	gate-to-source reverse leakage current, all other terminals shorted to source (single-gate types)	r _o	small-signal output resistance
C _{os}	feedthrough capacitance	I _{G1SSR}	gate-No. 1-to-source reverse leakage current, all other terminals shorted to source (dual-gate types)	r _{oss}	small-signal, short-circuit, common-source output resistance
C _{oss}	small-signal, common-source short-circuit output capacitance	I _{G2SSR}	gate-No.2-to-source reverse leakage current, all other terminals shorted to source (dual-gate types)	R _i	differential input resistance
C _{OP}	charge-pump capacitance	I _{GT}	gate trigger current; gate terminal current	r _i	small-signal input resistance
C _{rss}	small-signal, common-source short-circuit, reverse transfer capacitance	I _I	input current	r _{iss}	small-signal, short-circuit, common-source input resistance
e _i	input sensitivity	I _{IB}	input bias current	R _i	low-frequency input resistance
E _N	I/F noise voltage	I _{IBC}	internal bias current	R _{ON}	ON resistance; the ON-state resistance of an analog switch at specified input and load conditions.
e _N	low-frequency noise voltage; equivalent short-circuit input noise voltage (μV √ Hz)	I _{IO}	input offset current	ΔR _{ON}	ΔON resistance; the difference in ON-state resistance between any 2 analog switches at specified input and load conditions.
e _{N(total)}	wideband noise voltage referenced to input	α _{IIO}	average temperature coefficient of input offset current	S/N	signal-to-noise ratio
e _{O1} /e _{O2}	channel separation	ΔI _{IO} /ΔT	temperature coefficient of input offset current (drift)	SR	slew rate
E _{ON}	broadband output noise voltage	I _{LIM}	short-circuit limiting current	T _A	ambient temperature
f _{CL}	clock input frequency	I _{MTR}	current-mirror transfer ratio	t _d	delay time
f _{max}	maximum operating frequency	I _N	I/F noise current	t _{DR}	differential recovery time
f _p	charge-pump input-pulse frequency	I _N	equivalent open-circuit noise current (pA/√ Hz)	t _f	fall time
f _t	unity-gain crossover frequency; gain-bandwidth product	I _O	output current	t _{fφ}	input-pulse rise time
f _φ	input-pulse frequency	I _{O(DIFF)}	differential output current (sink)	THD	total harmonic distortion
G _p	power gain	I _{OO}	output offset current	t _{off}	turn-off time
G _m	forward transconductance (large-signal)		output leakage current, low	t _{on}	turn-on time
h _{FE}	static forward-current transfer ratio (beta)			t _r	rise time
h _{fe}	small-signal forward-current transfer ratio			t _{Rφ}	input-pulse rise time
I ⁺	dc supply current			t _{rr}	reverse recovery time
I ⁻	dc supply current			t _S	setup time
				t _{STG}	storage time
				t _W	pulse width
				V ⁺	DC positive supply voltage
				V ⁻	DC negative supply voltage
				V _{ABC}	amplifier bias voltage
				V _{BB}	substrate voltage
				V _{BE}	base-to-emitter voltage

Terms and Symbols

<p>$V_{BE(sat)}$ base-to-emitter saturation voltage</p> <p>$V_{(BR)CBO}$ collector-to-base breakdown voltage</p> <p>$V_{(BR)CES}$ collector-to-emitter breakdown voltage</p> <p>$V_{(BR)DI}$ dc breakdown voltage between diode and substrate</p> <p>$V_{(BR)R}$ dc reverse breakdown voltage</p> <p>$V_{(BR)EBO}$ emitter-to-base breakdown voltage</p> <p>$V_{(BR)GSSF}$ dc gate-to-source forward breakdown voltage, all other terminals shorted to source (single-gate types)</p> <p>$V_{(BR)G1SSF}$ dc gate-No.1-to-source forward breakdown voltage, all other terminals shorted to source (dual-gate types)</p> <p>$V_{(BR)G2SSF}$ dc gate No.2-to-source forward breakdown voltage, all other terminals shorted to source (dual-gate types)</p> <p>$V_{(BR)GSSR}$ dc gate-to-source reverse breakdown voltage, all other terminals shorted to source (single-gate types)</p> <p>$V_{(BR)G2SSR}$ dc gate-No.2-to-source reverse breakdown voltage, all other terminals shorted to source (dual-gate types)</p> <p>V_{CBO} collector-to-base voltage</p> <p>V_{CC} drain supply voltage used as a second positive supply voltage. It is $\leq V_{DD}$ and referenced to V_{SS}</p> <p>V_{CO} voltage controlled oscillator</p> <p>V_{CEO} collector-to-emitter voltage</p> <p>$V_{CEO(sus)}$ collector-to-emitter sustaining voltage</p> <p>V_{C10} collector-to-substrate voltage</p> <p>V_{CP} charge pump voltage</p> <p>V_{DD} drain supply voltage (the most positive supply voltage; always referenced to ground)</p> <p>V_{DG} drain-to-gate voltage (single-gate types)</p> <p>V_{DG1} drain-to-gate-No.1 voltage (dual-gate types)</p> <p>V_{DG2} drain-to-gate-No.2 voltage (single-gate types)</p> <p>V_{D10} diode-to-substrate voltage</p> <p>V_{DR} diode reverse voltage</p> <p>V_{DS} drain-to-source voltage</p> <p>V_{EE} source voltage (the most negative supply voltage in a 3-supply voltage system)</p> <p>V_F dc forward voltage</p> <p>$\Delta V_F/\Delta T$ temperature coefficient of forward voltage drop</p> <p>V_{GH} channel gate input voltage, high level</p> <p>V_{GL} channel gate input voltage, low level</p> <p>V_{GS} gate-to-source voltage</p> <p>$V_{GS(TH)}$ gate-to-source threshold voltage</p> <p>$V_{GS(Off)}$ gate-to-source cutoff voltage (single-gate types)</p> <p>V_{G1S} gate-No.1-to-source voltage (dual-gate type)</p> <p>$V_{G1S(Off)}$ gate-No.1-to-source cutoff voltage (dual-gate types)</p>	<p>V_{G2S} gate-No.2-to-source voltage (dual-gate types)</p> <p>$V_{G2S(off)}$ gate-No.2-to-source cutoff voltage (dual-gate types)</p> <p>V_i input voltage</p> <p>$V_i(Lim)$ input limiting voltage</p> <p>V_{ICR} common-mode input voltage range</p> <p>V_{iL} input-voltage, low level</p> <p>V_{iH} input-voltage, high level</p> <p>V_{iO} input offset voltage</p> <p>V_{iO} magnitude of input offset voltage</p> <p>$\Delta V_{iO}/\Delta T$ temperature coefficient of magnitude of input offset voltage</p> <p>$\Delta V_{iO}/\Delta T$ temperature coefficient of input offset voltage drift</p> <p>$\Delta V_{iO}/\Delta V^+$ positive input-offset-voltage sensitivity</p> <p>$\Delta V_{iO}/\Delta V^-$ negative input-offset-voltage sensitivity</p> <p>αV_{iO} average temperature coefficient of input-offset voltage</p> <p>$V_i(Lim)$ input limiting voltage (knee)</p> <p>V_{knee} protective diode knee voltage (protected gate types)</p> <p>V_N output noise voltage</p> <p>V_O output voltage</p> <p>$\Delta V_O/\Delta V^-$ dc supply voltage sensitivity</p> <p>$\Delta V_O/\Delta V^+$ dc supply voltage sensitivity</p> <p>$V_{O(rms)}$ open-loop output voltage swing</p> <p>ΔV_O output voltage temperature coefficient</p> <p>V_{Op-p} output voltage swing recovered at voltage</p> <p>$V_{O(af)}$ output voltage, low level; the voltage level at an output when the input logic conditions have been set to establish logic LOW output.</p> <p>V_{OL} output offset voltage</p> <p>V_{OO} output voltage, high level; the voltage level at an output when the input logic conditions have been set to establish a logic HIGH output.</p> <p>V_{OH} maximum output voltage</p> <p>V_{OM}^+ maximum output voltage</p> <p>V_{OM}^- maximum output voltage</p> <p>V_{QP} charge pump voltage</p> <p>V_{QPL} charge pump input voltage, low level</p> <p>V_{QPH} charge-pump input voltage, high level</p> <p>V_{REF} reference voltage</p> <p>V_{REG} regulated supply voltage</p> <p>V_{RR} supply voltage rejection ratio</p> <p>V_{TH} input threshold voltage</p> <p>V_Z zener voltage</p> <p>Y_{fs} magnitude of small-signal, common-source, short-circuit forward transfer admittance (transadmittance)</p> <p>Y_{is} small-signal, common-source, short-circuit, input-admittance (conductance, real part of admittance; susceptance, imaginary part of admittance)</p> <p>Y_{os} small-signal, common-source, short-circuit, output admittance</p>	<p>Y_{rs} magnitude of small-signal, common-source, short-circuit, reverse transadmittance</p> <p>$\angle Y_{rs}$ phase angle of small-signal, common-source, short-circuit, reverse transadmittance</p> <p>$(-)_rs$ angle of reverse transadmittance, common-source circuit</p> <p>Z_i input impedance</p> <p>Z_O output impedance</p> <p>Z_Z zener impedance</p> <p>ϕ phase angle</p> <p>ϕ phase margin</p> <p>η efficiency</p> <p>ϕ_L open-loop phase lag</p>
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Cross-Reference Directory for Linear Integrated Circuits

Industry Type	RCA Replacement Type	Industry Type	RCA Replacement Type	Industry Type	RCA Replacement Type
AD301AH	CA301AT,LM301AH	LM258AN	CA258AE	LM1845N	CA3120E
AD301AN	CA301AE,LM301AN	LM258AT	CA258AT	LM2111N	CA2111AE
AD741H	CA741T,LM741H	LM258H	CA258T	LM2901J	CA2901F
AD741N	CA741E,LM741N	LM258L	CA258T	LM2901N	LM2901N
AD741CH	CA741CT,LM741CH	LM258N	CA258E	LM2902N	LM2902N
AD741CN	CA741CE,LM741CN	LM258P	CA258E	LM2904N	CA2904E,LM2904N
AD2020	CA3162E	LM258T	CA258T	LM2904P	CA2904E,LM2904N
AMLM301AH	CA301AT,LM301AH	LM301AH	CA301AT,LM301AH	LM3011H	CA3011
AMLM301H	CA301T,LM301AH	LM301AL	CA301AT,LM301AH	LM3018H	CA3018
AMLM307H	CA307T,LM307H	LM301AN	CA301AE,LM301AN	LM3018AH	CA3018A
AMLM311H	CA311T,LM311H	LM301AP	CA301AE,LM301AN	LM3019H	CA3019
AM723HC	CA723CT,LM723CH	LM301AT	CA301AT,LM301AH	LM3026H	CA3026
AM723HM	CA723T,LM723H	LM301AV	CA301AE,LM301AN	LM3028AH	CA3028A
AM741HC	CA741CT,LM741CH	LM307H	CA307T,LM307H	LM3028B	CA3028B
AM741HM	CA741T,LM741H	LM307N	CA307E,LM307N	LM3039H	CA3039
AM747HC	CA747CT	LM307T	CA307T,LM307H	LM3045D	CA3045,CA3045F
AM747HM	CA747T	LM311H	CA311T,LM311H	LM3046N	CA3046
AM748HC	CA748CT,LM748CH	LM311L	CA311T,LM311H	LM3053H	CA3053
AM1458H	CA1458T,LM1458H	LM311N	CA311E,LM311N	LM3054N	CA3054
AM1558H	CA1558T,LM1558H	LM311P	CA311E,LM311N	LM3064H	CA3064
HA1-2630	CA3020	LM311T	CA311T,LM311H	LM3064N	CA3064E
HA1-2650	LM1558A,CA1558E	LM324N	CA324E,LM324N	LM3065N	CA3065
HA1-2655	LM1458H,CA1458E	LM339AJ	CA339AF	LM3066N	CA3066
HA1-2720	CA6078	LM339AN	CA339AE,LM339AN	LM3067N	CA3067
HA2-2311-5	CA311T,LM311H	LM339D	CA339F	LM3070N	CA3070
HA2-2520	CA3100T	LM339F	CA339F	LM3071N	CA3071
HA2-2650	CA1558T,LM1558H	LM339J	CA339F	LM3075N	CA3075
HA2-2655	CA1458T,LM1458H	LM339N	CA339E,LM339N	LM3086N	CA3086
HA2-2720	CA3078E	LM358AH	CA358AT	LM3089N	CA3089E,CA3189E
ITT1352N	CA1352E	LM358AN	CA358AE	LM3126N	CA3126E
ITT3064C	CA3064T	LM358AT	CA358AT	LM3146AN	CA3146AE
ITT3064N	CA3064E	LM358H	CA358T	LM3302J	LM3302F
ITT3065N	CA3065E	LM358L	CA358T	LM3302	LM3302N
		LM358N	CA358E	LM3401N	CA3401E
		LM358P	CA358E	M5141T	CA741CT,LM741CH
LF156H	CA081T	LM358T	CA358T	MC1310P	CA1310E
LF356H	CA081CT	LM393N	CA3290E	MC1352P	CA1352E
LF356J	CA081E	LM555CH	CA555CT,LM555CH	MC1357P	CA2111AE
LM100	CA3085E	LM555CN	CA555CE,LM555CN	MC1357PQ	CA2111AQ
LM124N	CA124E	LM555H	CA555T	MC1358P	CA3065
LM139J	CA139F	LM555N	CA555E,LM555N	MC1364G	CA3064T
LM139AN	CA139AE	LM723CH	CA723CT,LM723CH	MC1364P	CA3064E
LM139AJ	CA139AF	LM723CN	CA723CE,LM723CN	MC1370P	CA3070
LM139N	CA139E	LM723H	CA723T,LM723H	MC1371P	CA3071
LM158AH	CA158AT	LM723N	CA723E,LM723N	MC1375P	CA3075
LM158AN	CA158AE	LM741CH	CA741CT,LM741CH	MC1389P	CA3089E,CA3189E
LM158AT	CA158AT	LM741CN	CA741CE,LM741CN	MC1391P	CA1391E
LM158N	CA158E	LM741H	CA741T,LM741H	MC1394P	CA1394E
LM158P	CA158T	LM741N	CA741E,LM741N	MC1398P	CA1398E
LM158T	CA201AE	LM746N	CA3072	MC1455G	CA555CT,LM555CH
LM201AN	CA201AE	LM747CH	CA747CT	MC1455P1	CA555CE,LM555CN
LM201AP	CA201AE	LM747CN	CA747CE	MC1458G	CA1458T,LM1458H
LM201AV	CA201T	LM747H	CA747T	MC1458P1	CA1458E,LM1458N
LM201H	CA201E	LM748CH	CA748CT,LM748CH	MC1458T	CA1458T,LM1458H
LM201N	CA201T	LM748CN	CA748CE,LM748CN	MC1555G	CA555T
LM201T	CA201T	LM748H	CA748T,LM748H	MC1555P1	CA555CE,LM555CN
LM224N	CA224E	LM1310N	CA1310E	MC1558G	CA1558T,LM1558H
LM239AD	CA239AF	LM1391N	CA1391E	MC1558P1	CA1558E
LM239AF	CA239AF	LM1394N	CA1394E	MC1558T	CA1558T,LM1558H
LM239AJ	CA239AF	LM1458H	CA1458T,LM1458H	MC1723CG	CA723CT,LM723CH
LM239AN	CA239AE	LM1458N	CA1458E,LM1458N	MC1723CP	CA723CE,LM723CN
LM239D	CA239F	LM1558H	CA1558T,LM1558H	MC1723G	CA723T,LM723H
LM239F	CA239F	LM1558N	CA1558E	MC1741CG	CA741CT,LM741CH
LM239J	CA239F	LM1800N	CA758E	MC1741CP1	CA741CE,LM741CN
LM239N	CA239E	LM1820N	CA3123E	MC1741G	CA741T,LM741H
LM258AH	CA258AT				

Cross-Reference Directory for Linear Integrated Circuits

Industry Type	RCA Replacement Type	Industry Type	RCA Replacement Type	Industry Type	RCA Replacement Type
MC1747CG	CA747CT	SG748T	CA748T, LM748H	TL082CP	CA082E
MC1747G	CA747T	SG1458M	CA1458E, LM1458N	TL082ACP	CA082AE
MC1748CG	CA748CT, LM748CH	SG1458T	CA1458T, LM1458H	TL082BCP	CA082BE
MC1748CP1	CA748CE, LM748CN	SG1558T	CA1558T	TL083CN	CA083E
MC1748G	CA748T, LM748H	SG2524N	CA2524E	TL083ACN	CA083AE
MC3346P	CA3046	SG3018T	CA3018	TL084ACN	CA084AE
MC3386P	CA3086	SG3018AT	CA3018A	TL084CN	CA084E
MC34001BP	CA081AE	SG3058J	CA3058	TL084BCN	CA084BE
MC34001P	CA081E	SG3059J	CA3059	U5B7741312	CA741T, LM741H
MC34002BP	CA082AE	SG3079J	CA3079	U5B7741393	CA741CT, LM741CH
MC34002P	CA082E	SG3081N	CA3081	U5B7748312	CA748T, LM748H
MC3401P	CA3401E	SG3081J	CA3081F	U5B7748393	CA748CT, LM748CH
NE555P	CA555CE, LM555CN	SG3082N	CA3082	U5R7723312	CA723T, LM723H
NE555L	CA555CT, LM555CH	SG3082J	CA3082F	U5R7723393	CA723CT
NE555T	CA555CT, LM555CH	SG3083J	CA3083F	U6A7723393	CA723CE, LM723CN
NE555V	CA555CE, LM555CN	SG3401N	CA3401E	U9T7741393	CA741CE, LM741CN
PM741J	CA741T, LM741H	SG3524N	CA3524E	ULN2111A	CA2111AE
PM741CJ	CA741CT, LM741CH	SN76115N	CA1310E	ULN2111N	CA2111AQ
PM747K	CA747T	SN76116N	CA758E	ULN2114A	CA3072
PM747CK	CA747CT	SN76242N	CA3070	ULN2124A	CA3070
RC555NB	CA555CE, LM555CN	SN76243AN	CA3071	ULN2125A	CA3120E
RC555T	CA555CT, LM555CH	SN76264N	CA3072	ULN2127A	CA3071
RC723CN	LM723CN	SN76267N	CA3067	ULN2129A	CA3075
RC723DB	CA723CE, LM723CN	SN76298N	CA1398E	ULN2137A	CA3123E
RC723T	CA723CT, LM723CH	SN76564N	CA3064	ULN2165A	CA3065
RC1458NB	CA1458E, LM1458N	SN76565N	CA3064E	ULN2210A	CA1310E
RC1458T	CA1458T, LM1458T	SN76635N	CA3123E	ULN2212B	CA3012
RC3401DB	CA3401E	SN76650N	CA1352E	ULN2262A	CA3126Q
RC741DB	CA741CE, LM741CN	SN76666N	CA3065	ULN2264A	CA3064
RC741NB	CA741CE, LM741CN	SN76675N	CA3075	ULN2267A	CA3067
RC741T	CA741T, LM741H	SN76676P	CA3076	ULN2269A	CA3121E
RC747DB	CA747CE	SN76689N	CA3089E, CA3189E	ULN2289A	CA3089E, CA3189E
RC747T	CA747T	SSS301AJ	CA301AT, LM301AH	ULN2298A	CA1398E
RM555T	CA555T, LM555H	SSS301AP	CA301AE, LM301AN	ULX2244A	CA758E
RM723T	CA723T, LM723H	SSS741CJ	CA741CT, LM741CH	μ A301AH	CA301AT, LM301AH
RM741T	CA741T, LM741H	SSS1458J	CA1458T, LM1458H	μ A307H	CA307T, LM307H
RM747T	CA747T	SSS1558J	CA1558T, LM1558H	μ A307T	CA307E, LM307N
RM1558T	CA1558T, LM1558H	TDA2002V	CA2002	CA3001AT	CA301AE, LM301AN
SE555L	CA555T	TDA2002H	CA2002M	μ A311H	CA311T, LM311H
SE555N	CA555E	TBB0747	CA747CT	μ A311T	CA311E, LM311H
SE555P	CA555E	TBB0748	CA748CT, LM748CH	μ A555HC	CA555CT, LM555CH
SE555T	CA555T	TBB0748B	CA748CE, LM748CN	μ A555HM	CA555T
SFC2301A	CA301AT, LM301AH	TBB1458B	CA1458E, LM1458N	μ A555TC	CA555CE, LM555CN
SFC2301ADC	CA301AE, LM301AN	TBC0747	CA747T	μ A720PC	CA3123E
SFC2307	CA307T, LM307H	TCA270	CA270	μ A723CA	CA723CE, LM723CN
SFC2311	CA311T, LM311H	TDA3081N	CA3081	μ A723CL	CA723CT, LM723CH
SFC2741C	CA741CT, LM741CH	TDA3082N	CA3082	μ A723CN	CA723CE, LM723CN
SFC2741M	CA741T, LM741H	TDA3083N	CA3083	μ A723HC	CA723CT, LM723CH
SFC2748DC	CA748CE, LM748CN	TDA7607	CA7607E	μ A723HM	CA723T, LM723H
SFC2748C	CA748CT, LM748CH	TDA7611	CA7611E	μ A723MN	CA723E, LM723N
SG301AN	CA301AE, LM301AN	TDB0723	CA723CT, LM723CH	μ A723ML	CA723T, LM723H
SG301AT	CA301AT, LM301AH	TDB0723A	CA723CE, LM723CN	μ A723PC	CA723CE, LM723CN
SG307N	CA307E, LM307N	TDC0723	CA723T, LM723H	μ A741CN	CA741CE, LM741CN
SG307T	CA307T, LM307H	TL080ML	CA080T	μ A741CL	CA741CT, LM741CH
SG311M	CA311E, LM311H	TL080AML	CA080AT	μ A741CP	CA741CE, LM741CN
SG311T	CA311T, LM311H	TL080CL	CA080CT	μ A741CT	CA741CE, LM741CN
SG723CN	CA723CE, LM723CN	TL080CP	CA080E	μ A741HC	CA741CT, LM741CH
SG723CT	CA723CT, LM723CH	TL080ACP	CA080AE, CA080BE	μ A741HM	CA741T, LM741H
SG723T	CA723T, LM723H	TL081ML	CA081T	μ A741ML	CA741T, LM741H
SG741CN	CA741CE, LM741CN	TL081AML	CA081AT	μ A741MN	CA741E, LM741N
SG741CT	CA741CT, LM741CH	TL081CL	CA081CT	μ A741MP	CA741E, LM741N
SG741T	CA741T, LM741H	TL081CP	CA081E	μ A741PC	CA741E, LM741CN
SG747CN	CA747CE	TL081ACP	CA081AE	μ A746PC	CA3072
SG747CT	CA747CT	TL081BCP	CA081BE	μ A747CA	CA747CE
SG747T	CA747T	TL082ML	CA082T	μ A747CL	CA747CT
SG748CN	CA748CE, LM748CN	TL082	CA082CT	μ A747CN	CA747CE
SG748CT	CA748CT, LM748CH				

Cross-Reference Directory for Linear Integrated Circuits

Industry Type	RCA Replacement Type	Industry Type	RCA Replacement Type
μ A747HC	CA747CT	μ A3019HM	CA3019
μ A747HM	CA747T	μ A3026HM	CA3026
μ A747ML	CA747T	μ A3036HM	CA3036
μ A747MN	CA747E	μ A3039HM	CA3039
μ A747PC	CA747CE	μ A3045DM	CA3045, CA3045F
μ A747A	CA747E	μ A3046DC	CA3046
μ A748CL	CA748CT, LM748CH	μ A3054PC	CA3054
μ A748CN	CA748CE, LM748CN	μ A3064HC	CA3064
μ A748CP	CA748CE, LM748CN	μ A3064PC	CA3064E
μ A748CT	CA748CT, LM748CH	μ A3065PC	CA3065
μ A748HC	CA748CT, LM748CH	μ A3066PC	CA3066
μ A748HM	CA748T, LM748H	μ A3075PC	CA3075
μ A748ML	CA748T, LM748H	μ A3086DC	CA3086F
μ A748MN	CA748E, LM748N	μ A3089E	CA3089E, CA3189E
μ A748MP	CA748E, LM748N	μ A3401P	CA3401E
μ A748T	CA748E, LM748N	μ PC151A	CA741CT, LM741CH
μ A748TC	CA748CE, LM748CN	μ PC151C	CA741CE, LM741CN
μ A758PC	CA758E	μ PC157A	CA301AT, LM301AH
μ A780PC	CA3070	μ PC157C	CA301AE, LM301AN
μ A781PC	CA3071	μ PC251A	CA747CT
μ A787PC	CA3126Q	μ PC251C	CA747CE
μ A1391T	CA1391E	μ PC301AC	CA301AE, LM301AN
μ A1394T	CA1394E	μ PC311C	CA311E, LM311N
μ A1458HC	CA1458T, LM1458H	μ PC324C	CA324E, LM324N
μ A1458TC	CA1458E, LM1458N	μ PC339C	CA339E, LM339N
μ A1558HM	CA1558T	μ PC741C	CA741CE, LM741CN
μ A3018HM	CA3018	μ PC1458C	CA1458E, LM1458N
μ A3018AHM	CA3018A		

LM Branded Linear IC's

RCA supplies the following Linear IC's branded with the industry standard "LM" Brand. Technical Data on LM Branded types is identical to the corresponding CA Branded types. See chart below.

Type	Equivalent CA Type	Data Bulletin File No.	Page
LM1458H	CA1458T	531	38
LM1458N	CA1458E	531	38
LM1558H	CA1558T	531	38
LM201H	CA201T	786	28
LM2901N	*		
LM2902N	*		
LM2904N	CA2904E	1019	38
LM301AH	CA301AT	786	28
LM301AN	CA301AE	786	28
LM307H	CA307T	785	34
LM307N	CA307E	785	34
LM311H	CA311T	797	270
LM311N	CA311E	797	270
LM324N	CA324E	796	104
LM3302N	*		
LM339AN	CA339AE	795	301

Type	Equivalent CA Type	Data Bulletin File No.	Page
LM339N	CA339E	795	301
LM358N	CA358E	1019	98
LM555CH	CA555CT	834	653
LM555CN	CA555CE	834	653
LM723CH	CA723CT	788	520
LM723CN	CA723CE	788	520
LM723H	CA723T	788	520
LM723N	CA723E	788	520
LM741CH	CA741CT	531	38
LM741CN	CA741CE	531	38
LM741H	CA741T	531	38
LM741N	CA741E	531	38
LM748CH	CA748CT	531	38
LM748CN	CA748CE	531	38
LM748H	CA748T	531	38
LM748N	CA748E	531	38

*No CA Branded part type conforms to industry standard data

The EVP option

For systems designers, the key to cost-effective device procurement is often found in determining the right level of reliability. How much reliability? At what cost?

For semiconductor manufacturer and user alike, the answer has always been the same. As much reliability as the application requires at the lowest practical cost.

The screening programs of RCA employ this philosophy to achieve Linear IC reliability goals in both standard product and military high-reliability product.

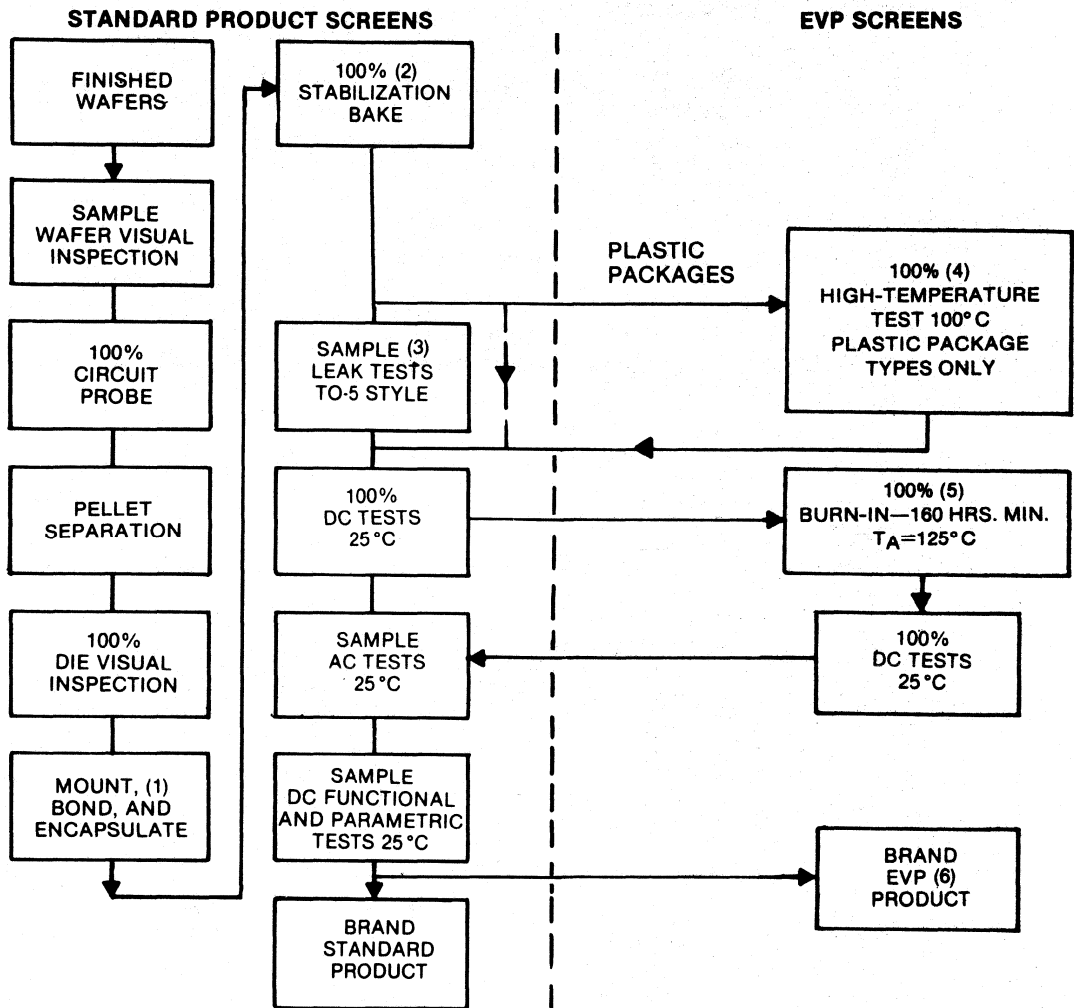
As both integrated circuits and their application become more complex, an increasing number of linear IC users find the cost-effective answer to reliability requirements in a new level of reliability screening. One which for the intended use, is more effective than standard product but does not involve the higher costs required to achieve military reliability levels.

This new cost-effective approach to enhanced commercial reliability is provided by the RCA Extra Value Program.

The Extra Value Program adds a burn-in and additional testing to the comprehensive real-time controls and test procedures carried out on standard plastic and TO-5-style product. The enhanced product of the Extra Value Program achieves AQL levels as shown in the chart below.

TEST	EVP PRODUCT
100% High-Temperature Continuity or Functional Test at 100 °C	Plastic-package types only
Sample Leak Test	TO-5-style package types only; Gross leak rate = 1×10^{-5} Atm.cc/sec. max.; Fine leak rate = 5×10^{-8} Atm.cc/sec. max.
100% Burn-In	160 Hrs. Min. at 125 °C per MIL-STD-883A Method 1015.1
AQL DC Parametric Tests	0.25% Max.
AQL DC Functional Tests	0.15% Max.
Marking	Standard Part No. with Blue Dot

PROCESS FLOW CHART



- (1) Epoxy mount and cure; ultrasonic aluminum wire bond on TO-5-style or thermosonic gold-wire bond on plastic types; encapsulate in TO-5-style or plastic dual-in-line package.
- (2) Stabilization bake 6 hours at 175°C for plastic-package types, 16 hours at 200°C for TO-5-style types.
- (3) Gross leak rate of 1×10^{-5} Atm.cc/sec max. and fine leak rate of 5×10^{-8} Atm.cc/sec max.
- (4) High-temperature (i.e., heat-pipe, hot-rail) test
 - (a) automatic test for continuity on each terminal at 100°C for array types.
 - (b) continuity or functional gain test at 100°C for op-amps, comparators, and voltage regulators.
- (5) 100% dc test before and after burn-in per MIL-STD-883A Method 1015.1
- (6) Brand EVP product surviving both Enhancement Screens with Standard Type Number plus blue dot.

The extra value of burn-in

Quality relates to the percentage of defective units at "time zero". It is a measure of devices dead-on-arrival (DOA). While the total absence of even a single defective unit in any lot of devices received from the semiconductor manufacturer may be the ideal goal, it is an impractical one.

Testing experience and a complete understanding of failure mechanisms tell us that every increment of improvement over the standard 0.65% AQL carries a price tag which becomes disproportionately high relative to the number of line rejects it will eliminate.

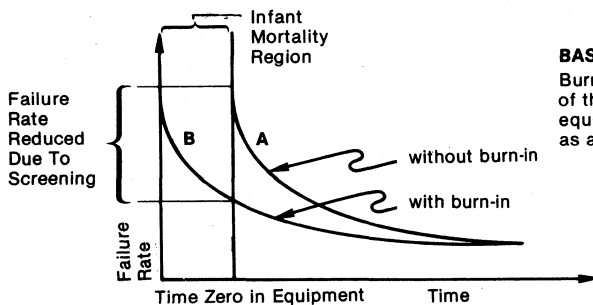
Application experience shows that the simple reduction of AQL does in no way guarantee an improvement in field-failure rates.

Reliability, in contrast to the zero-time aspects of quality, is a measure of the maintenance of quality through time in actual system environment.

Component burn-in is effective in screening out temperature- and time-dependent mechanisms that would normally escape detection under a 100% final electrical test.

Thus, the Extra Value Program offers greater cost effectiveness in achieving field reliability than any program which relies solely on reduced outgoing or incoming inspection levels.

The basic theory of burn-in and the type of improvement which can be expected through reduced device infant mortality is depicted in the chart below.



BASIC THEORY OF SCREENING

Burn-in and screening eliminate a major percentage of the infant mortality. Component life in equipment is translated from curve A to curve B as a result of burn-in

EVP SCREENING	ORDERING INFORMATION		
Burn-In Time — 160 Hrs. Min. Burn-In Temperature — 125°C Hot Continuity Test Temperature — 100°C	Package Type	Standard Type No.	Extra Value Type No.
	Plastic Dual-In-Line	CA741E	CA741EX
	TO-5 Style	CA3140T	CA3140TX

Operational Amplifiers

Technical Data

General Purpose	Page	General Purpose Wideband	Page	Variable	Page
Single Unit		Single Unit		High Current	
CA101	28	CA080*	83	CA3094	213
CA201	28	CA081*	83	Micropower	
CA301A	28	CA3008	114	CA3060	224
CA307	34	CA3008A	121	CA3078	237
CA741	38	CA3010	114	CA3080	245
CA748	38	CA3010A	121	CA3440*	254
CA3105	46	CA3015	114	CA6078A	79
CA3152*	48	CA3015A	121	Dual Unit	
CA3193*	52	CA3016	114	CA3280*	260
CA3420*	63	CA3016A	121		
CA3493*	68	CA3021	129		
CA6741*	79	CA3022	129		
Dual Unit		CA3023	129		
CA082*	83	CA3029	114		
CA083*	83	CA3029A	121		
CA158	93	CA3030	114		
CA258	93	CA3030A	121		
CA358	93	CA3037	114		
CA747	38	CA3037A	121		
CA1458	38	CA3038	114		
CA1558	38	CA3038A	121		
CA2904	38	CA3100*	135		
Quad Unit		CA3130*	141		
CA084*	83	CA3140*	156		
CA124	104	CA3160*	176		
CA224	104	Dual Unit			
CA324	104	CA3240*	193		
CA3401	110	CA3260*	208		

*BiMOS types

•Low-noise versions of CA741 and CA3078

Op Amp, Comparator, and OTA

Selection Chart Pages 24 — 27

Op-Amp, Comparator, and OTA Selection Chart

Type #	Description	Basic Ratings			Input Characteristics @ 25°C				
		Compens. Internal External	V _r , V Max. V	I _s Max. nA	V _{io} Max. mV	I _b Max. nA	I _{io} Max. nA	V _{ICR} (Plus) V	V _{ICR} (Minus) V
CA080E	Single BiMOS Op-Amp with High Slew Rate	E	±18	2.8	15	.050	.030	10	10
CA080T-S		E	±18	2.8	6	.040	.020	12	12
CA080AE		E	±18	2.8	6	.040	.020	12	12
CA080AT-S		E	±18	2.8	3	.040	.020	12	12
CA080BE		E	±18	2.8	3	.030	.010	12	12
CA080CT-S		E	±18	2.8	15	.050	.030	10	10
CA081E	Single BiMOS Op-Amp with High Slew Rate	I, E	±18	2.8	15	.050	.030	10	10
CA081T-S		I, E	±18	2.8	6	.040	.020	12	12
CA081AE		I, E	±18	2.8	6	.040	.020	12	12
CA081AT-S		I, E	±18	2.8	3	.040	.020	12	12
CA081BE		I, E	±18	2.8	3	.030	.010	12	12
CA081CT-S		I, E	±18	2.8	15	.050	.030	10	10
CA082E	Dual BiMOS Op-Amp with High Slew Rate	I	±18	5.6	15	.050	.030	10	10
CA082T-S		I	±18	5.6	6	.040	.020	12	12
CA082AE		I	±18	5.6	6	.040	.020	12	12
CA082AT-S		I	±18	5.6	3	.040	.020	12	12
CA082BE		I	±18	5.6	3	.030	.010	12	12
CA082CT-S		I	±18	5.6	15	.050	.030	10	10
CA083E	Dual BiMOS Op-Amp with High Slew Rate	I	±18	5.6	15	.050	.030	10	10
CA083AE		I	±18	5.6	6	.040	.020	12	12
CA083BE		I	±18	5.6	3	.030	.010	12	12
CA084E	Quad BiMOS Op-Amp with High Slew Rate	I	±18	11.2	15	.050	.030	10	10
CA084AE		I	±18	11.2	6	.040	.020	12	12
CA084BE		I	±18	11.2	3	.030	.010	12	12
CA101	General Purpose Op-Amp	E	±22	3.0	5.0	500	200	12	12
CA124 ¹¹	Quad Op-Amp	I	±16	8	5	150	30	V ⁻ -1.5	0
CA139 ¹¹	Quad Volt Comparator	NA	±18	8	5	100	25	V ⁻ -1.5	0
CA139A ¹¹	Quad Volt-Comparator	NA	±18	8	2	100	25	V ⁻ -1.5	0
CA158 ¹¹	Dual Op-Amp-General Purpose	E	±16	3	5	150	30	V ⁻ -1.5	0
CA158A ¹¹	Dual Op-Amp-General Purpose	E	±16	3	2	50	10	V ⁻ -1.5	0
CA201	General Purpose Op-Amp	E	±22	3	7.5	1,500	500	12	12
CA224 ¹¹	Quad Op Amp	I	±16	8	7	250	50	V ⁻ -1.5	0
CA239 ¹¹	Quad Volt Comparator	NA	±18	8	5	250	50	V ⁻ -1.5	0
CA258 ¹¹	Dual Op-Amp-General Purpose	E	±16	3	5	150	30	V ⁻ -1.5	0
CA258A ¹¹	Dual Op-Amp-General Purpose	E	±16	3	3	80	15	V ⁻ -1.5	0
CA301A	General Purpose Op-Amp	E	±18	3	7.5	250	50	12	12
CA307	General Purpose Op-Amp	I	±18	3	7.5	300	50	12	12
CA311	Single Volt Comparator	NA	±18	8	7.5	250	50	14	14
CA324 ¹¹	Quad Op-Amp	I	±16	8	7	250	50	V ⁻ -1.5	0
CA339 ¹¹	Quad Voltage Comparator	NA	±18	8	5	250	50	V ⁻ -1.5	0
CA339A ¹¹	Quad Voltage Comparator	NA	±18	8	2	250	50	V ⁻ -1.5	0
CA358 ¹¹	Dual Op-Amp General Purpose	E	±16	3	7	250	50	V ⁻ -1.5	0
CA358A ¹¹	Dual Op-Amp General Purpose	E	±16	3	3	100	30	V ⁻ -1.5	0
CA741	Single-General Purpose Op-Amp	I	±22	2.8	5	500	200	12	12
CA741C	Single-General Purpose Op-Amp	I	±18	2.8	6	500	200	12	12
CA747	Dual 741	I	±22	5.6	5	500	200	12	12
CA747C	Dual 741	I	±18	5.6	6	500	200	12	12
CA748	Single-General Purpose Op-Amp	E	±22	2.8	5	500	200	12	12
CA748C	Single-General Purpose Op-Amp	E	±18	2.8	6	500	200	12	12
CA1458	Dual 748	I	±18	5.6	6	500	200	12	12
CA1558	Dual 748	I	±22	5.6	5	500	200	12	12
CA3008	General Purpose Op-Amp	E	±8	9	5	12,000	5,000	.50	4
CA3008A	General Purpose Op-Amp	E	±8	9	2	4,000	1,500	.50	4
CA3010	General Purpose Op-Amp	E	±8	9	5	12,000	5,000	.50	4
CA3010A	General Purpose Op-Amp	E	±8	9	2	4,000	5,000	.50	4
CA3015	General Purpose Op-Amp	E	±16	21	5	24,000	5,000	.65	8
CA3016	General Purpose Op-Amp	E	±16	21	5	24,000	5,000	.65	8
CA3029	General Purpose Op-Amp	E	±8	9	5	12,000	5,000	.50	4
CA3029A	General Purpose Op-Amp	E	±8	9	2	4,000	1,500	.50	4
CA3030	General Purpose Op-Amp	E	±16	21	5	24,000	5,000	.65	8
CA3030A	General Purpose Op-Amp	E	±16	21	2	6,000	1,600	.65	8
CA3037	General Purpose Op-Amp	E	±8	9	5	12,000	5,000	.50	4
CA3037A	General Purpose Op-Amp	E	±16	9	2	4,000	1,500	.50	4
CA3038	General Purpose Op-Amp	E	±16	21	5	24,000	5,000	.65	8
CA3038A	General Purpose Op-Amp	E	±16	21	2	6,000	1,600	.65	8
CA3060D	OTA - Triple Amplifier	E	±7	3.6	5	5,000	1,000	4.3	5
CA3060AD	and Array	E	±18	3.6	5	5,000	1,000	12	12
CA3060BD	I _{ABC} = 100 μA	E	±18	3.6	5	5,000	1,000	12	12
CA3060E	I _{ABC} = 100 μA	E	±18	3.6	5	5,000	1,000	12	12

Output Characteristics				AC Characteristics @ 25°C			Package Characteristics ⁴		Page #
V _{OUT} ± ⁵ Min. V	V _{OUT} ± ³ Min. V	R _L for V _{OUT} OHMS	AOL ¹ Min V/V	BW ² Typ MHz	Slew Rate ² Typ V/μs	Temp ³ Range IMC	Plastic Ceramic	TO5 Metal CAN	
24 V _{pp}	24 V _{pp}	10K	25K	5	13	C	8E		83
24 V _{pp}	24 V _{pp}	10K	50K	5	13	M		8T, 8S	
24 V _{pp}	24 V _{pp}	10K	50K	5	13	C	8E		
24 V _{pp}	24 V _{pp}	10K	50K	5	13	M	8E		
24 V _{pp}	24 V _{pp}	10K	50K	5	13	C		8T, 8S	
24 V _{pp}	24 V _{pp}	10K	25K	5	13	C	8E		
24 V _{pp}	24 V _{pp}	10K	25K	5	13	C		8T, 8S	83
24 V _{pp}	24 V _{pp}	10K	50K	5	13	M	8E		
24 V _{pp}	24 V _{pp}	10K	50K	5	13	C		8T, 8S	
24 V _{pp}	24 V _{pp}	10K	50K	5	13	M	8E		
24 V _{pp}	24 V _{pp}	10K	50K	5	13	C	8E		
24 V _{pp}	24 V _{pp}	10K	25K	5	13	C		8T, 8S	
24 V _{pp}	24 V _{pp}	10K	25K	5	13	C	8E		83
24 V _{pp}	24 V _{pp}	10K	50K	5	13	M	8E		
24 V _{pp}	24 V _{pp}	10K	50K	5	13	C		8T, 8S	
24 V _{pp}	24 V _{pp}	10K	50K	5	13	M	8E		
24 V _{pp}	24 V _{pp}	10K	50K	5	13	C	8E		
24 V _{pp}	24 V _{pp}	10K	25K	5	13	C		8T, 8S	
24 V _{pp}	24 V _{pp}	10K	25K	5	13	C	14E		83
24 V _{pp}	24 V _{pp}	10K	50K	5	13	C	14E		
24 V _{pp}	24 V _{pp}	10K	50K	5	13	C	14E		
24 V _{pp}	24 V _{pp}	10K	25K	5	13	C	14E		83
24 V _{pp}	24 V _{pp}	10K	50K	5	13	C	14E		
24 V _{pp}	24 V _{pp}	10K	50K	5	13	C	14E		
10	10	2K	50K	1.0	10 non comp	M	8E	8T, 8S	28
V ⁻ -1.5V	0	2K	50K	1.0	.5	M	14E		104
V _{SAT} = .5V		5.1K	50K	t _r = 300 ns	t _r = 1.3 μs	M	14E		301
V _{SAT} = .5V		5.1K	50K	t _r = 300 ns	t _r = 1.3 μs	M	14E		
V ⁻ -1.5V	0	2K	50K	1.0	.5	M	8E	8T, 8S	93
V ⁻ -1.5V	0	2K	50K	1.0	.5	M	8E	8T, 8S	
+10	+10	2K	20K	1.0	10 non comp	C	8E	8T, 8S	28
V ⁻ -1.5V	0	2K	25K	1.0	.5	I	14E		104
V _{SAT} = .5V		2K	50K	t _r = 300 ns	t _r = 1.3 μs	I	14E		301
V ⁻ -1.5V	0	2K	50K	1.0	.5	I	8E	8T, 8S	93
V ⁻ -1.5V	0	2K	50K	1.0	.5	I	8E	8T, 8S	
+10	-10	2K	25K	1.0	10 non comp	C	8E	8T, 8S	28
+10	-10	2K	25K	2	.5	C	8E	8T, 8S	34
V _{SAT} = 1.5V		5K	200K	Response time 200 ns		C	8E	8T, 8S	270
V ⁻ -1.5V	0	2K	25K	1.0	.5	C	14E		104
V _{SAT} = .5V		2K	50K	t _r = 300 ns	t _r = 1.3 μs	C	14E		301
V _{SAT} = .5V		2K	50K	t _r = 300 ns	t _r = 1.3 μs	C	14E		
V ⁻ -1.5V	0	2K	25K	1.0	.5	C	8E	8T, 8S	93
V ⁻ -1.5V	0	2K	25K	1.0	.5	C	8E	8T, 8S	
10	-10	2K	50K	1.0	.5	M	8E	8T, 8S	38
10	-10	2K	20K	1.0	.5	C	8E	8T, 8S	
10	-10	2K	50K	1.0	.5	M	14E	10T	38
10	-10	2K	20K	1.0	.5	C	14E	10T	
10	-10	2K	50K	1.0	.5	M	8E	8T, 8S	38
10	-10	2K	20K	1.0	.5	C	8E	8T, 8S	
10	-10	2K	20K	1.0	.5	C	8E	8T, 8S	38
10	-10	2K	50K	1.0	.5	M	8E	8T, 8S	38
2	-2	2K	.7K	.20 ¹⁰	3	M	14K		114
2	-2	2K	.7K	.20 ¹⁰	3	M	14K		121
2	-2	2K	.7K	.20 ¹⁰	3	M		12T	114
2	-2	2K	.7K	.20 ¹⁰	3	M		12T	121
6	-6	2K	2K	.20 ¹⁰	3	M		12T	114
6	-6	2K	2K	.20 ¹⁰	3	M	14K		114
2	-2	2K	.7K	.20 ¹⁰	7	M	14E		114
2	-2	2K	.7K	.20 ¹⁰	7	C	14E		121
6	-6	2K	2K	.20 ¹⁰	3	C	14E		114
6	-6	2K	2K	.20 ¹⁰	3	C	14E		121
2	-2	2K	.7K	.20 ¹⁰	7	C	14D		114
2	-2	2K	.7K	.20 ¹⁰	7	M	14D		121
6	-6	2K	2K	.20 ¹⁰	3	M	14D		114
6	-6	2K	2K	.20 ¹⁰	3	M	14D		121
4.6	-5.8	∞	gm=30μmho	.110	8	M	16D		224
12	-12	∞	gm=30μmho	.110	8	M	16D		
12	-12	∞	gm=30μmho	.110	8	M	16D		
12	-12	∞	gm=30μmho	.110	8	I	16E		

Op-Amp, Comparator, and OTA Selection Chart

Type #	Description	Basic Ratings			Input Characteristics @ 25°C					
		Compens. Internal External	V _s , V Max.	I _s Max. nA	V _{IO} Max. mV	I _B Max. nA	I _{IO} Max. nA	V _{ICR} (Plus) V	V _{ICR} (Minus) V	
CA3078	Micropower Op Amp	E	±7	.130	4.5	170	32	5	5	
CA3078A	Micropower Op-Amp	E	±18	.025	3.5	12	2.5	5	5	
CA3080	High Slew Rate OTA	E	±18	1.2	5	5,000	600	12	12	
CA3080A	High Slew Rate OTA	E	±18	1.2	2	5,000	600	12	12	
CA3094	Programmable	E	±12	.4	5	5,000	2,000	12	14	
CA3094A	Power Switch/Amplifier	E	±18	.4	5	5,000	2,000	12	14	
CA3094B	(OTA)	E	±22	.4	5	5,000	2,000	12	14	
CA3100	Wideband BiMOS Op-Amp	E, I	±18	10.5	5	2,000	400	12	12	
CA3130 ¹¹	BiMOS Op-Amp with	E	±8	15	15	.050	.030	10	0	
CA3130A ¹¹	MOS Input and	E	±8	15	5	.030	.020	10	0	
CA3130B ¹¹	MOS Output	E	±8	15	2	.020	.010	10	0	
CA3140	BiMOS Op-Amp with	I	±18	6	15	.050	.030	11	15	
CA3140A	MOS Input and	I	±18	6	5	.030	.020	12	15	
CA3140B	Bipolar Output	I	±22	6	2	.020	.010	12	15	
CA3160 ¹¹	BiMOS Op-Amp with	I, E	±8	15	15	.050	.030	10	0	
CA3160A ¹¹	MOS Input and	I, E	±8	15	5	.030	.020	10	0	
CA3160B ¹¹	MOS Output	I, E	±8	15	2	.020	.010	10	0	
CA3193 ⁸	Precision - 5μV/°C, Neg. Null	I	±18	3.5	.500	40	10	10	12	
CA3193A ⁸	Precision - 3μV/°C, Neg. Null	I	±18	3.5	.200	20	5	10	12	
CA3193B ⁸	Precision — 2 μV/°C Neg. Null	I	±22	3.5	.075	15	3	10	12	
CA3240	Dual BiMOS Op-Amp	I	±18	12	15	.050	.030	11	15	
CA3240A	With MOS Input and Bipolar Output	I	±18	12	5	.040	.020	12	15	
CA3260 ¹¹	Dual BiMOS Op Amp	I	±8	15.5	15	.050	.030	10	0	
CA3260A ¹¹	With MOS Input	I	±8	15.5	5	.030	.020	10	0	
CA3260B ¹¹	and MOS Output	I	±8	15.5	2	.020	.010	10	0	
CA3280 ¹²	Dual OTA	E	±18	4.8	3.0	5,000	700	13	13	
CA3280A ¹²	Dual OTA	E	±18	4.8	0.5	5,000	700	13	13	
CA3290	Dual BiMOS	NA	±18	3	20	.050	.030	V ⁺ -3.8V	V ⁻	
CA3290A	Comparator with	NA	±18	3	10	.040	.025	V ⁺ -3.8V	V ⁻	
CA3290B	MOS Input & Bipolar Output	NA	±22	3	6	.030	.020	V ⁺ -3.8V	V ⁻	
CA3401	Quad Single Supply Op-Amp (Norton)	I	±18	14	NA	300	NA	NA	NA	
CA3420	Low-Supply Voltage	I	±11	.550	10	.003	.0020	NS	NS	
CA3420A	Low Current BiMOS	I	±11	.550	5	.003	.0020	.2	1.0	
CA3420B	Op-Amp (±1V Operation)	I	±11	.550	2	.001	.0007	.2	1.0	
CA3420	Low-Supply Voltage	I	±11	.700	10	.003	.0020	8.5	10	
CA3420A	Low-Current BiMOS	I	±11	.700	5	.003	.0020	9.0	10	
CA3420B	Op-Amp (±10V Operation)	I	±11	.700	2	.001	.0007	9.0	10	
CA3440 ⁷	Nano Power	I	±12.5	.017	10	.050	.030	3.5	5.0	
CA3440A ⁷	BiMOS Op-Amps	I	±12.5	.017	5	.040	.020	3.5	5.0	
CA3440B ⁷		I	±12.5	.017	2	.030	.010	3.5	5.0	
CA3493 ⁸	Precision - 5μV/°C - Pos. Null	I	±18	3.5	.500	40	10	10	12	
CA3493A ⁸	Precision - 3 μV/°C - Pos. Null	I	±18	3.5	.200	20	5	10	12	
CA3493B ⁸	Precision - 2 μV/°C - Pos. Null	I	±22	3.5	.075	15	3	10	12	
CA6078A ^{9, 10}	Low Burst Noise Micropower Op-Amp	E	±18	.025	3.5	12	3.5	14	14	
CA6741 ⁹	Low Burst Noise General Purpose Op-Amp	I	±22	2.8	5.0	500	200	12	12	

NOTES:

- A_{OL} value is for a load resistor as specified in the output characteristics chart. If the load is different it will be displayed under the A_{OL} value.
For OTA's the A_{OL} value is replaced by gm.
- Slew rate values on externally compensated amplifiers will differ with compensation.
For comparator circuits the slew rate and BW values are replaced by response times.
- Temperature range's are defined as:
C = 0° C to 70° C
I = 40° C to 85° C
M = -55° C to 125° C
- Package suffix's are defined as:
T = TO-5
E = Plastic
K = Ceramic Flat Pak
D = Ceramic — Dual in Line
S = TO-5 formed for 8 or 12 Lead Plastic
- Output characteristics are defined for load resistors as defined in the chart. If there are characteristics for two load resistors they will be displayed by a slanted line.
- CA3100 AC Characteristics:
Slew rate characteristics in the chart is for C_c = 10 pf Av = 1, V_o = 10 V (pulse)
For C_c = 0_{pf}, Av = 10, SR = 70 V/μs typ., 50 V/μs min.

Operational Amplifiers

Output Characteristics				AC Characteristics @ 25°C			Package Characteristics ⁴		Page #
V _{OUT} + ⁵ Min. V	V _{OUT} - ⁵ Min. V	R _L for V _{OUT} OHMS	AOL ¹ Min V/V	BW ² Typ MHz	Slew Rate ² Typ V/μs	Temp ³ Range IMC	Plastic Ceramic	TO5 Metal CAN	
5.1	-5.1	10K	25K	.002	1.5	C	8E	8T, 8S	237
5.1	-5.1	10K	40K	.0003	0.5	M	8E	8T, 8S	
12	12	∞	gm = 9.6 μmho	2	50	C	8E	8T, 8S	245
12	12	∞	gm = 9.6 μmho	2	50	M	8E	8T, 8S	
14.95	14.2	2K	20K	30	50	M	8E	8T, 8S	213
14.95	14.2	2K	20K	30	50	M	8E	8T, 8S	
14.95	14.2	2K	20K	30	50	M	8E	8T, 8S	
9	-9	2K	630	38	25 ^b	M	8E	8T, 8S	135
14.99/12	.001	∞/2K	50K	15/C _c = 0	30/C _c = 0	M	8E	8T, 8S	141
14.99/12	.001	∞/2K	50K	15/C _c = 0	30/C _c = 0	M	8E	8T, 8S	
14.99/12	.001	∞/2K	100K	15/C _c = 0	30/C _c = 0	M	8E	8T, 8S	
12	-14	2K	20K	4.5	9	M	8E	8T, 8S	156
12	-14	2K	20K	4.5	9	M	8E	8T, 8S	
12	-14	2K	50K	4.5	9	M	8E	8T, 8S	
14.99/12	.001	∞/2K	50K	4	10	M	8E	8T, 8S	176
14.99/12	.001	∞/2K	50K	4	10	M	8E	8T, 8S	
14.99/12	.001	∞/2K	100K	4	10	M	8E	8T, 8S	
13	-13	2K	100K	1.2	.25	C	8E	8T, 8S	52
13	-13	2K	316K	1.2	.25	I	8E	8T, 8S	
13	-13	2K	1000K	1.2	.25	M	8E	8T, 8S	
12	-14	2K	20K	4.5	9	M	8E, 14E1	8T, 8S	193
12	-14	2K	20K	4.5	9	M	8E, 14E1	8T, 8S	
14.99/11	.001	∞/2K	50K	4	10	M	8E	8T, 8S	208
14.99/11	.001	∞/2K	50K	4	10	M	8E	8T, 8S	
14.99/11	.001	∞/2K	100M	4	10	M	8E	8T, 8S	
12	-12	∞	50K/∞	9	125	M	16E		260
12.5	-13.3	∞	50K/∞	9	125	M	16E		
V _{SAT} = .4V		(4mA)	25K	t _r = 1.2 μs	t _r = 200 ns	M	8E, 14E1	8T, 8S	291
V _{SAT} = .4V		(4mA)	25K	t _r = 1.2 μs	t _r = 200 ns	M	8E, 14E1	8T, 8S	
V _{SAT} = .4V		(4mA)	50K	t _r = 1.2 μs	t _r = 200 ns	M	8E, 14E1	8T, 8S	
13.5	.10	10K	1K	5	.6	M	14E		110
.90	-.85	∞	10K/10KΩ	.5	.5	M	8E	8T, 8S	63
.90	-.85	∞	20K/10KΩ	.5	.5	M	8E	8T, 8S	
.90	-.95	∞	20K/10KΩ	.5	.5	M	8E	8T, 8S	
9.7	-9.7	∞	10K/10KΩ	.5	.5	M	8E	8T, 8S	63
9.7	-9.7	∞	20K/10KΩ	.5	.5	M	8E	8T, 8S	
9.7	-9.7	∞	20K/10KΩ	.5	.5	M	8E	8T, 8S	
3	-3	10K	10K	.063	.03	M	8E	8T, 8S	254
3	-3	10K	10K	.063	.03	M	8E	8T, 8S	
3	-3	10K	32K	.063	.03	M	8E	8T, 8S	
13	-13	2K	100K	1.2	.25	C	8E	8T, 8S	68
13	-13	2K	316K	1.2	.25	I	8E	8T, 8S	
13	-13	2K	1000K	1.2	.25	M	8E	8T, 8S	
13.7	-13.7	10K	40K	.0003	1.5	M		8T, 8S	79
12	-12	2K	50K	1.0	.50	M		8T, 8S	79

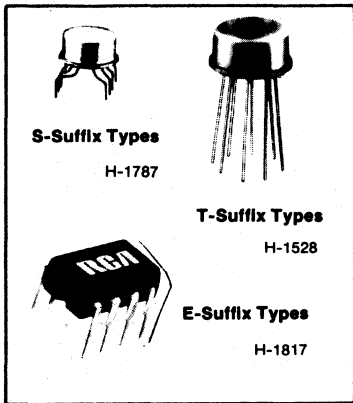
NOTES (cont'd):

7. For CA3440 series R_{SET} = 10 MΩ.
8. CA3493 is equivalent to CA3193 with the exception of nulling & pin out. CA3493 is pos nulling with pinout equivalent μA725. CA3193 has CA741 pinout.
Temp COEFF = ΔV_{IO}/ΔT

	Typ	Max	
CA3193/CA3493	1.0	5	μV/°C
CA3193A/CA3493A	1.0	3	μV/°C
CA3193B/CA3493B	.60	2	μV/°C
9. CA6078T and CA6741T are for applications where low noise (burst + 1/f) is a prime requirement.
10. -3 db BW
11. Characteristics shown are for single supply operation.
12. CA3280 characteristics @ I_{ABC} = 500 μA except V_{IO}, I_B, I_O which are at I_{ABC} = 1 mA.

Linear Integrated Circuits

CA101, CA201, CA301A Types



Operational Amplifiers

For Commercial, Industrial, and Military Applications

Features:

- Short-circuit protection and latch-free operation
- Unity-gain phase compensation with a single 30-pF capacitor
- Replacement for industry types 101, 201, 301A
- CA301A Slew Rate (Summing ampl.) 10 V/μs

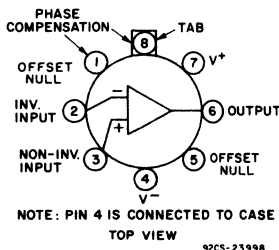
The RCA-CA101, CA201, and CA301A are general-purpose, high-gain operational amplifiers for use in military, industrial, and commercial applications.

These types, which are externally phase compensated, permit a choice of operation for optimum high-frequency performance at a selected gain; unity-gain compensation can be obtained with a single 30-pF capacitor.

All types are available in 8-lead TO-5 style packages with standard leads (T suffix), and with dual-in-line formed leads ("DIL-CAN", S suffix). The CA301A is also available in the 8-lead dual-in-line plastic package ("MINI-DIP"), E suffix, and in chip form (H suffix).

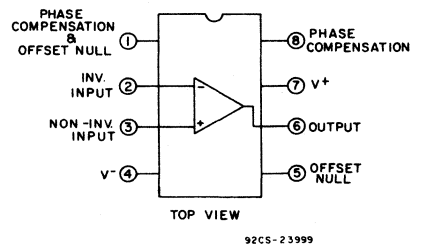
Applications:

- Long-interval integrator
- Timers
- Sample-and-hold circuits
- Summing amplifiers
- Multivibrators
- Comparators
- Instrumentation
- AC/DC converters
- Inverting amplifiers
- Sine- & square-wave generators
- Capacitance multipliers & simulated inductors



a — TO-5 Style package for all types

T-Suffix
S-Suffix



b — Plastic package for CA301A

E-Suffix

Fig. 1 - Functional diagrams.

Operational Amplifiers

CA101, CA201, CA301A Types

Maximum Ratings, Absolute Maximum Values at $T_A = 25^\circ\text{C}$:

DC SUPPLY VOLTAGE (Between V_+ and V_- Terminals):	
CA101, CA201	44 V
CA301A	36 V
DC INPUT VOLTAGE	
(For supply voltages less than ± 15 V, the Input Voltage rating is equal to the DC Supply Voltage)	
DIFFERENTIAL INPUT VOLTAGE	± 30 V
OUTPUT SHORT-CIRCUIT DURATION	Indefinite*
DEVICE DISSIPATION:	
UP TO $T_A = 75^\circ\text{C}$	500 mW
Above $T_A = 75^\circ\text{C}$ Derate linearly at	6.67 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:	
Operating —	
CA101	-55 to $+125^\circ\text{C}$
CA201, CA301A	0 to $+70^\circ\text{C}$
Storage (All types)	
-65 to $+150^\circ\text{C}$	
LEAD TEMPERATURE (During Soldering):	
At a distance $1/16'' \pm 1/32''$ (1.59 ± 0.79 mm) from case for 10 seconds max.	
$+265^\circ\text{C}$	

* At $T_A \leq 70^\circ\text{C}$ and $T_c \leq 125^\circ\text{C}$ (CA101); $T_A \leq 55^\circ\text{C}$ and $T_c \leq 70^\circ\text{C}$ (CA201, CA301A).

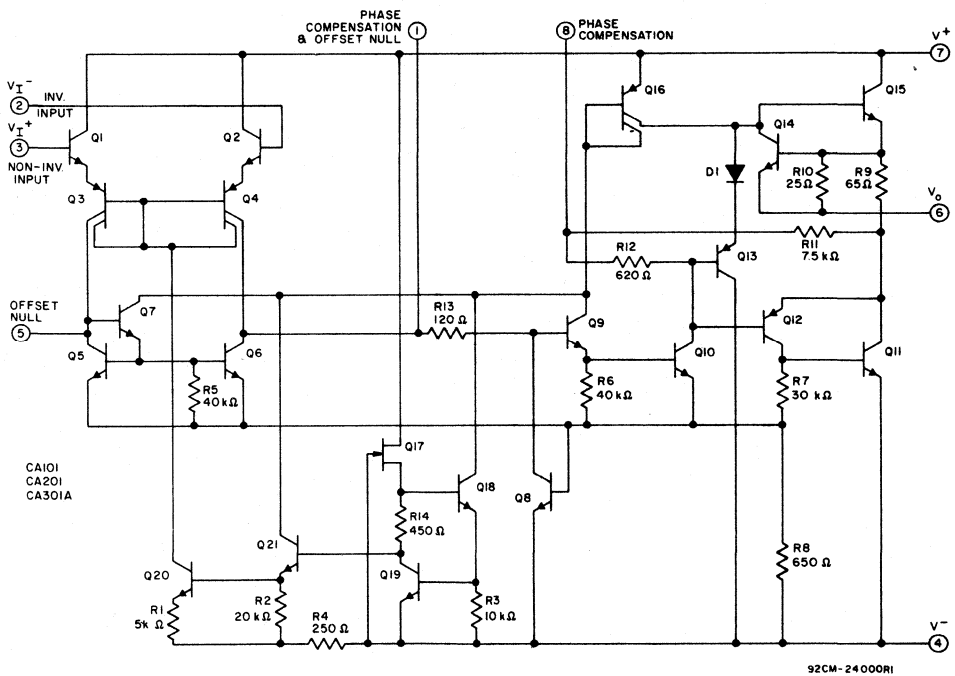


Fig. 2 - Schematic diagram.

Linear Integrated Circuits

CA101, CA201, CA301A Types

ELECTRICAL CHARACTERISTICS

CHARACTERISTICS	TEST CONDITIONS Δ	LIMITS									UNITS
	Supply Voltage (V_{\pm}) = 5 to 15 V	CA101			CA201			CA301A			
		Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage V_{io}	$T_A=25^{\circ}\text{C}$ $R_s \leq 10\text{k}\Omega$	—	1	5	—	2	7.5	—	—	—	mV
	$R_s \leq 50\text{k}\Omega$	—	—	—	—	—	—	—	2	7.5	
	$R_s \leq 10\text{k}\Omega$	—	—	6	—	—	10	—	—	—	
	$R_s \leq 50\text{k}\Omega$	—	—	—	—	—	—	—	—	10	
Average Temperature Coefficient of Input Offset Voltage αV_{io}	$R_s \leq 10\text{k}\Omega$	—	6	—	—	10	—	—	—	—	$\mu\text{V}/^{\circ}\text{C}$
	$R_s \leq 50\Omega$	—	3	—	—	6	—	—	—	—	
Average Temperature Coefficient of Input Offset Current αI_{io}	-55°C to $+25^{\circ}\text{C}$	—	—	—	—	—	—	—	—	—	nA/ $^{\circ}\text{C}$
	0°C to $+25^{\circ}\text{C}$	—	—	—	—	—	—	—	0.02	0.6	
	$+25^{\circ}\text{C}$ to $+70^{\circ}\text{C}$	—	—	—	—	—	—	—	0.01	0.3	
	$+25^{\circ}\text{C}$ to $+125^{\circ}\text{C}$	—	—	—	—	—	—	—	—	—	
Input Offset Current I_{io}	$T_A = 0^{\circ}\text{C}$	—	—	—	—	150	750	—	—	—	nA
	$T_A = 25^{\circ}\text{C}$	—	40	200	—	100	500	—	3	50	
	$T_A = 70^{\circ}\text{C}$	—	—	—	—	50	400	—	—	—	
	$T_A = 125^{\circ}\text{C}$	—	10	200	—	—	—	—	—	—	
	$T_A = -55^{\circ}\text{C}$	—	100	500	—	—	—	—	—	70	
Input Bias Current I_{ib}	$T_A = -55^{\circ}\text{C}$	—	0.28	1.5	—	—	—	—	—	—	μA
	$T_A = 0^{\circ}\text{C}$	—	—	—	—	0.32	2	—	—	—	
	$T_A = 25^{\circ}\text{C}$	—	0.12	0.5	—	0.25	1.5	—	0.07	0.25	
Supply Current I_{\pm}	$T_A=25^{\circ}\text{C}$ $V_{\pm}=15\text{V}$	—	—	—	—	—	—	—	1.8	3	mA
	$V_{\pm}=20\text{V}$	—	1.8	3	—	1.8	3	—	—	—	
	$T_A=125^{\circ}\text{C}$ $V_{\pm}=20\text{V}$	—	1.2	2.5	—	—	—	—	—	—	
Open-Loop Differential Voltage Gain A_{OL}	$T_A=25^{\circ}\text{C}$ $V_{\pm}=15\text{V}$ $V_o=\pm 10\text{V}$ $R_L \geq 2\text{k}\Omega$	50	160	—	20	150	—	25	160	—	V/mW
	$V_{\pm}=15\text{V}$ $V_o=\pm 10\text{V}$ $R_L \geq 2\text{k}\Omega$	25	—	—	15	—	—	15	—	—	
Input Resistance R_i	$T_A=25^{\circ}\text{C}$	0.3	0.8	—	0.1	0.4	—	0.5	2	—	M Ω
Output Voltage Swing V_{OPP}	$V_{\pm}=15\text{V}$ $R_L=10\text{k}\Omega$	± 12	± 14	—	± 12	± 14	—	± 12	± 14	—	V
	$V_{\pm}=15\text{V}$ $R_L=2\text{k}\Omega$	± 10	± 13	—	± 10	± 13	—	± 10	± 13	—	
Common-Mode Input-Voltage Range V_{ICR}	$V_{\pm}=15\text{V}$	± 12	—	—	± 12	—	—	± 12	—	—	V
	$V_{\pm}=20\text{V}$	—	—	—	—	—	—	—	—	—	
Common-Mode Rejection Ratio $CMRR$	$R_s \leq 10\text{k}\Omega$	70	90	—	65	90	—	—	—	—	dB
	$R_s \leq 50\text{k}\Omega$	—	—	—	—	—	—	70	90	—	
Supply-Voltage Rejection Ratio $PSRR$	$R_s \leq 10\text{k}\Omega$	70	90	—	70	90	—	—	—	—	dB
	$R_s \leq 50\text{k}\Omega$	—	—	—	—	—	—	70	90	—	

Δ Characteristics applicable over operating temperature range (T_A) as shown below, unless otherwise specified:

CA101: -55 to $+125^{\circ}\text{C}$; CA201, CA301A: 0 to 70°C

Operational Amplifiers CA101, CA201, CA301A Types

TYPICAL STATIC CHARACTERISTICS TYPE CA101

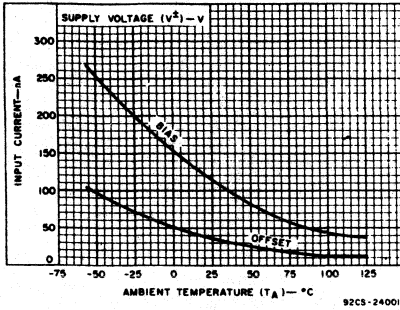


Fig. 3 - Input current (I_{iO} , I_{iB}) vs. temperature.

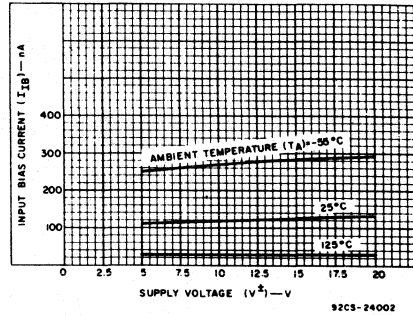


Fig. 4 - Input bias current vs. supply voltage.

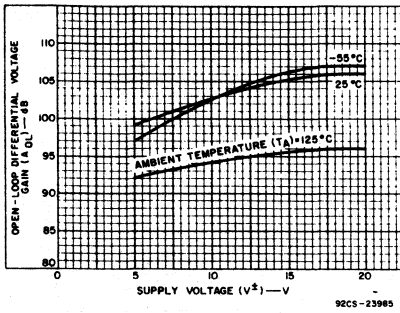


Fig. 5 - Voltage gain vs. supply voltage.

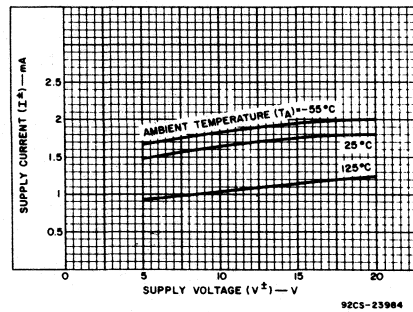


Fig. 6 - Supply characteristics.

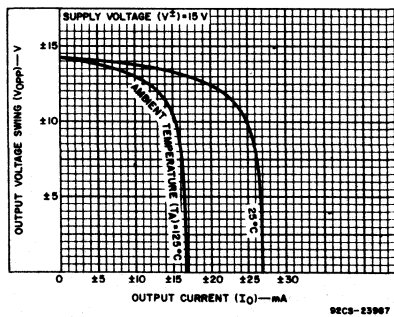


Fig. 7 - Output characteristics.
TYPE CA201

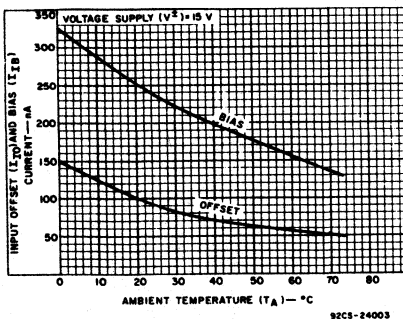


Fig. 8 - Input current (I_{iO} , I_{iB}) vs. temperature.

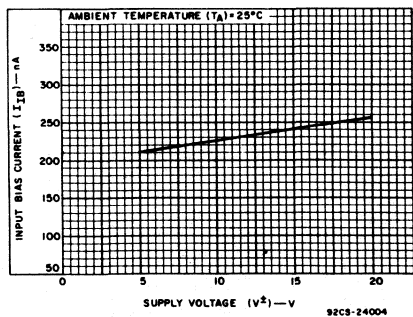


Fig. 9 - Input bias current (I_{iB}) vs. supply voltage.

Linear Integrated Circuits

CA101, CA201, CA301A Types

TYPICAL STATIC CHARACTERISTICS (Cont'd)

TYPE CA201

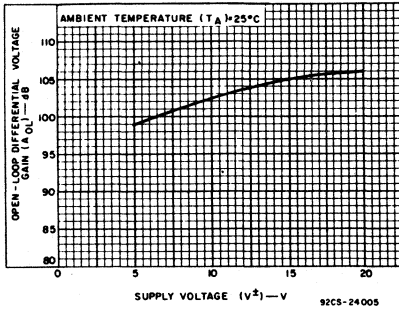


Fig. 10 - Voltage gain vs. supply voltage.

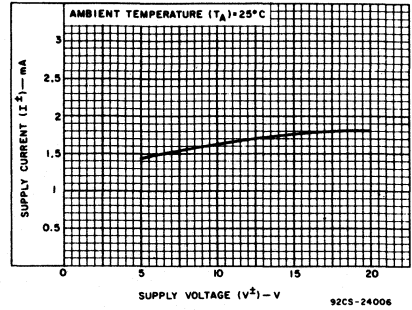


Fig. 11 - Supply characteristics.

TYPE CA301A

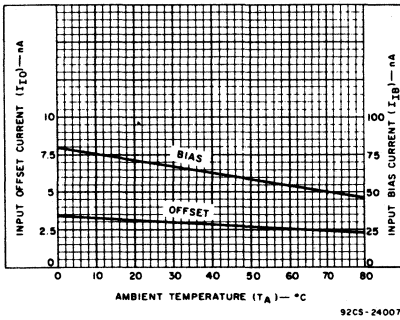


Fig. 12 - Input current (I_{IO} , I_{IB}) vs. temperature.

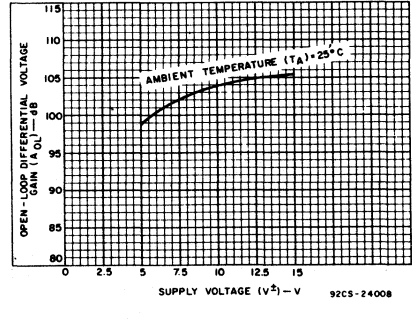


Fig. 13 - Voltage gain vs. supply voltage.

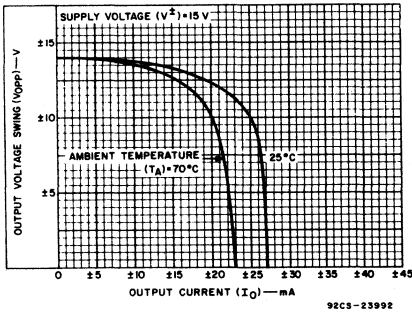


Fig. 14 - Output characteristics.

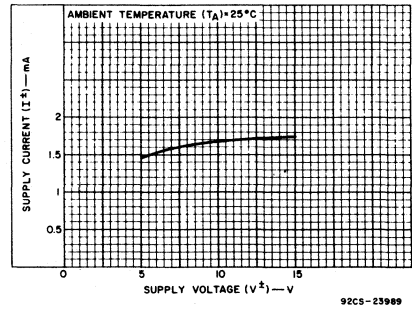


Fig. 15 - Supply characteristics.

TYPICAL DYNAMIC CHARACTERISTICS

TYPES CA101, CA201, CA301A

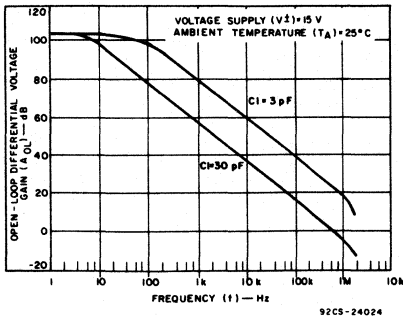


Fig. 16 - Voltage gain vs. frequency.

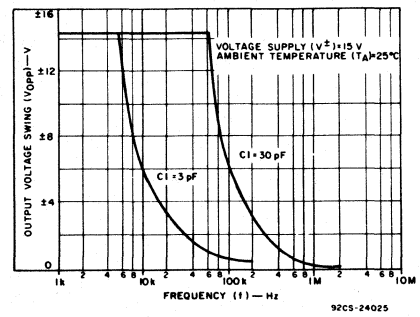


Fig. 17 - Output voltage swing vs. frequency.

CA101, CA201, CA301A Types

TYPICAL DYNAMIC CHARACTERISTICS (Cont'd)
FOR TYPES CA101, CA201 AND CA301A

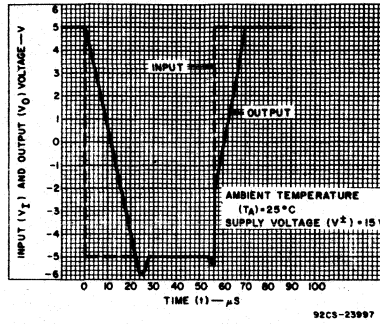


Fig. 18 - Voltage follower pulse response.

TYPE CA301A

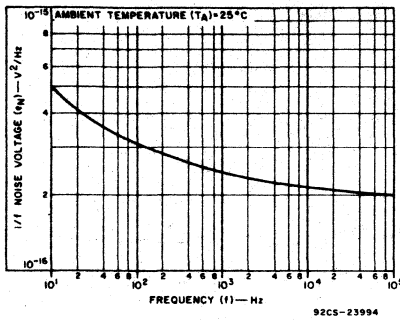


Fig. 19 - 1/f noise voltage vs. frequency.

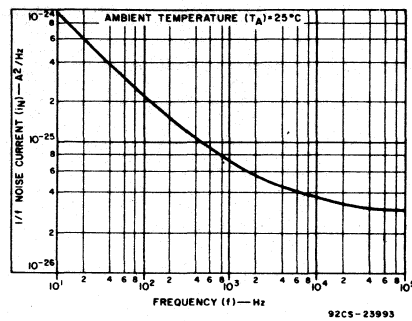
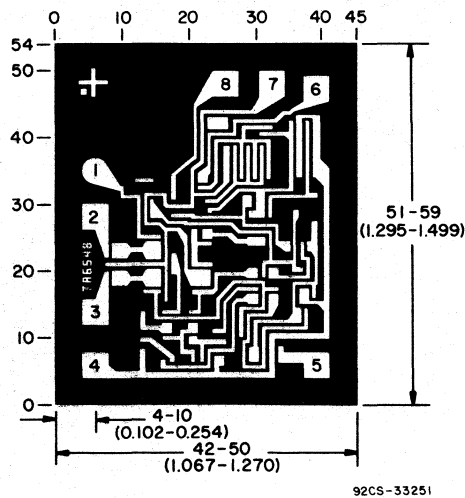


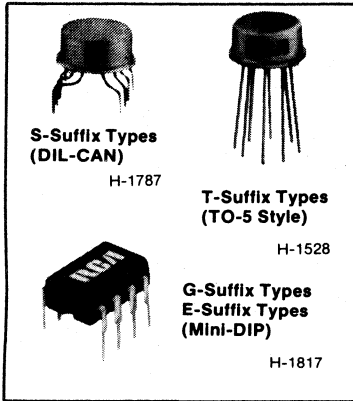
Fig. 20 - 1/f noise current vs. frequency.



Dimensions and pad layout for CA301H.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch).

CA307



Operational Amplifier

For Military, Industrial, and Commercial Applications

Applications:

- Long-interval integrators
- Timers
- Sample-and-hold circuits
- Summing amplifiers
- Multivibrators

The RCA CA307 is a general-purpose operational amplifier intended for use in military, industrial, and commercial applications. A 30-pF on-chip capacitor provides internal frequency compensation.

The CA307 is available in 8-lead TO-5 style packages with

standard leads (T suffix), with dual-in-line formed leads ("DIL-CAN", S suffix), in the 8-lead dual-in-line plastic package ("MINI-DIP", E suffix), and in chip form (H suffix).

The CA307 is a direct replacement for industry type 307 in packages with similar terminal arrangements.

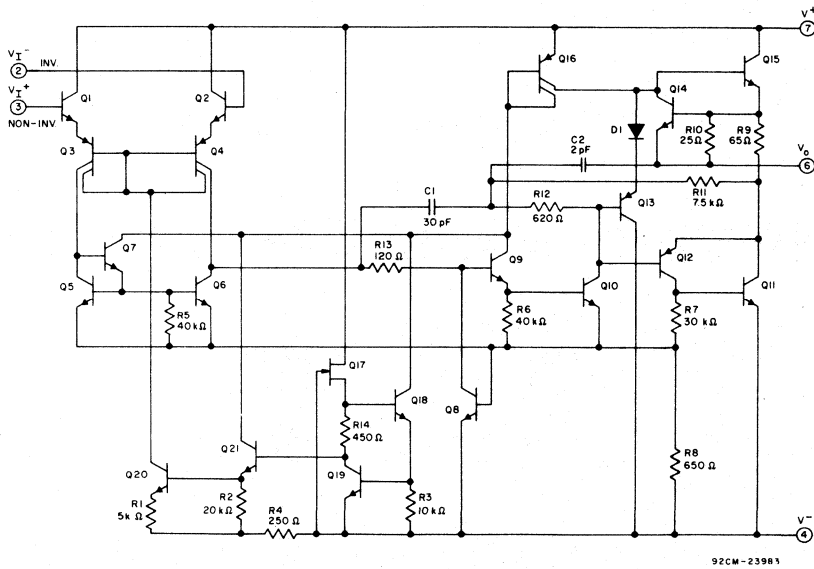


Fig. 1 - Schematic diagram of CA307.

Maximum Ratings, Absolute Maximum Values at $T_A = 25^\circ\text{C}$:

DC SUPPLY VOLTAGE (Between V^+ and V^- Terminals):	
CA307	36 V
DC INPUT VOLTAGE	± 15 V
(For supply voltages less than ± 15 V, the absolute maximum input voltage is equal to the supply voltage)	
DIFFERENTIAL INPUT VOLTAGE	± 30 V
OUTPUT SHORT-CIRCUIT DURATION*	Indefinite
DEVICE DISSIPATION UP TO $T_A = 70^\circ\text{C}$	500 mW
Above $T_A = 70^\circ\text{C}$ Derate linearly at	6.67 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:	
Operating	0°C to $+70^\circ\text{C}$
Storage	-65°C to $+150^\circ\text{C}$
LEAD TEMPERATURE (During Soldering):	
At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10 seconds max.	$+265^\circ\text{C}$

*For type CA307 continuous short circuit is allowed for Case Temperature to $+70^\circ\text{C}$ and ambient temperature to $+55^\circ\text{C}$.

+Types CA307 E, S, and T can be operated over the temperature range of -55 to $+125^\circ\text{C}$, although the published limits for certain electrical specifications apply only over the temperature range of 0 to 70°C .

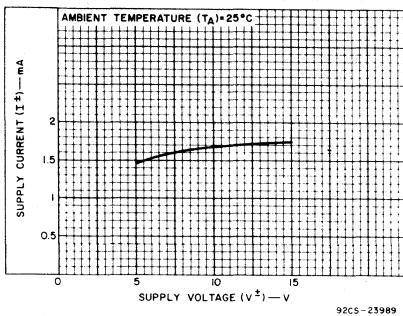


Fig. 2 - Supply current vs. supply voltage.

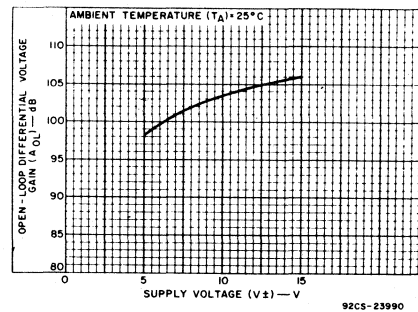


Fig. 3 - Open-loop differential voltage gain vs. supply voltage.

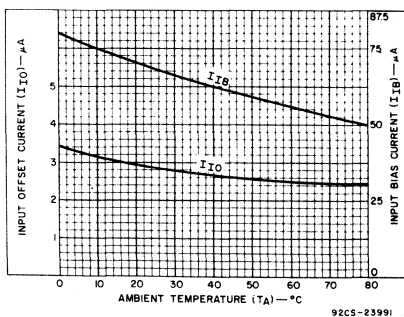


Fig. 4 - Input offset and input bias current vs. ambient temperature.

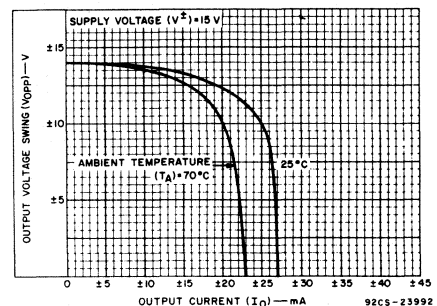


Fig. 5 - Output voltage swing vs. output current.

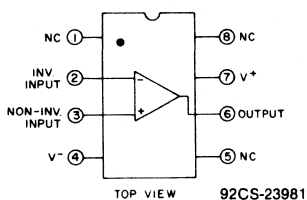
Linear Integrated Circuits

CA307

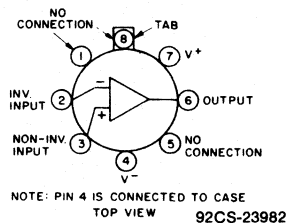
ELECTRICAL CHARACTERISTICS

CHARACTERISTIC		TEST CONDITIONS Δ	LIMITS			UNITS
		Supply Voltage (V_{\pm}) = 5 V to 15 V	CA307			
			Min.	Typ.	Max.	
Input Offset Voltage	V_{io}	$T_A = 25^{\circ}\text{C}$, $R_s \leq 50\text{ k}\Omega$	—	2	7.5	mV
		$R_s \leq 50\text{ k}\Omega$	—	—	10	
Average Temperature Coefficient of Input Offset Voltage	αV_{io}		—	6	30	$\mu\text{V}/^{\circ}\text{C}$
Input Offset Current	I_{io}		—	—	70	nA
		$T_A = 25^{\circ}\text{C}$	—	3	50	
Average Temperature Coefficient of Input Offset Current	αI_{io}	+25 to 70 $^{\circ}\text{C}$	—	0.01	0.3	nA/ $^{\circ}\text{C}$
		0 to +25 $^{\circ}\text{C}$	—	0.02	0.6	
Input Bias Current	I_{ib}		—	—	300	nA
		$T_A = 25^{\circ}\text{C}$	—	70	250	
Supply Current	I_{\pm}	$T_A = +125^{\circ}\text{C}$, $V_{\pm} = 20\text{ V}$	—	—	—	mA
		$T_A = 25^{\circ}\text{C}$, $V_{\pm} = 15\text{ V}$	—	1.8	3	
Open-Loop Differential Voltage Gain	A_{OL}	$V_{\pm} = 15\text{ V}$, $V_o = \pm 10\text{ V}$, $R_L \geq 2\text{ k}\Omega$	15	—	—	V/mV
		$V_{\pm} = 15\text{ V}$, $V_o = \pm 10\text{ V}$, $R_L \geq 2\text{ k}\Omega$, $T_A = 25^{\circ}\text{C}$	25	160	—	
Input Resistance	R_i	$T_A = 25^{\circ}\text{C}$	0.5	2	—	M Ω
Output Voltage Swing	V_{OPP}	$V_{\pm} = 15\text{ V}$, $R_L = 10\text{ k}\Omega$	± 12	± 14	—	V
		$V_{\pm} = 15\text{ V}$, $R_L = 2\text{ k}\Omega$	± 10	± 13	—	
Input Voltage Range	V_{ICR}	$V_{\pm} = 15\text{ V}$	± 12	—	—	V
Common-Mode Rejection Ratio	CMRR	$R_s \leq 50\text{ k}\Omega$	70	90	—	dB
Supply-Voltage Rejection Ratio	PSRR	$R_s \leq 50\text{ k}\Omega$	70	96	—	dB

Δ Characteristics applicable over operating temperature range $T_A = 0$ to 70 $^{\circ}\text{C}$ unless otherwise specified.



FUNCTIONAL DIAGRAM FOR PLASTIC PACKAGE



FUNCTIONAL DIAGRAM FOR TO-5 STYLE PACKAGES

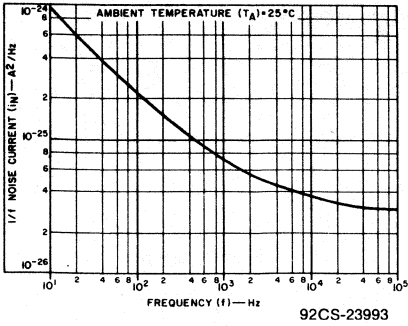


Fig. 6 - 1/f noise current vs. frequency.

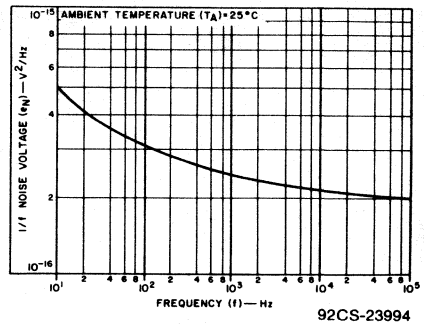


Fig. 7 - 1/f noise voltage vs. frequency.

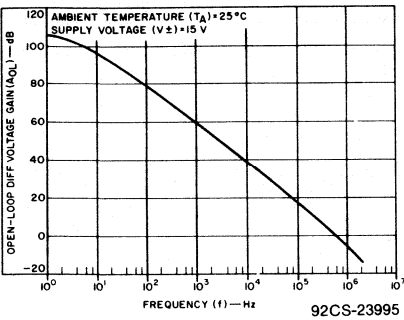


Fig. 8 - Open-loop differential voltage gain vs. frequency.

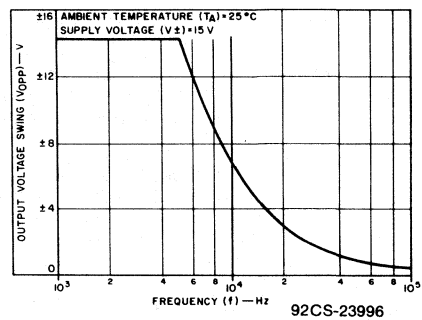


Fig. 9 - Output voltage swing vs. frequency.

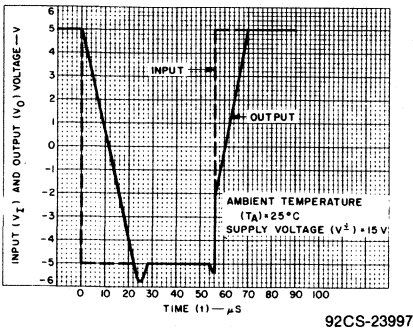
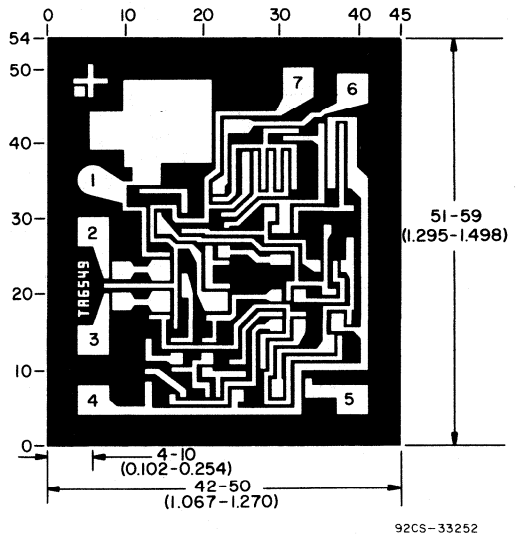


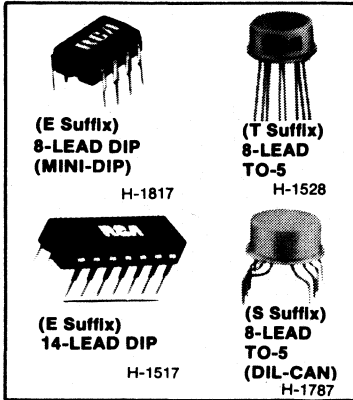
Fig. 10 - Input and output voltage vs. time.



Dimensions and pad layout for CA307H.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

CA741, CA747, CA748, CA1458, CA1558 Types



Operational Amplifiers

High-Gain Single and Dual Operational Amplifiers
For Military, Industrial and Commercial Applications

Features:

- *Input bias current (all types):*
500 nA max.
- *Input offset current (all types):*
200 nA max.

Applications:

- *Comparator*
- *DC amplifier*
- *Integrator or differentiator*
- *Multivibrator*
- *Narrow-band or band-pass filter*
- *Summing amplifier*

The RCA-CA1458, CA1558 (dual types); CA741C, CA741 (single-types); CA747C, CA747 (dual types); and CA748C, CA748 (single types) are general-purpose, high-gain operational amplifiers for use in military, industrial, and commercial applications.

These monolithic silicon integrated-circuit devices provide output short-circuit protection and latch-free operation. These types also feature wide common-mode and differential-mode signal ranges and have low-offset voltage nulling capability when used with an appropriately valued potentiometer. A 5-megohm potentiometer is used for offset nulling types CA748C, CA748 (See Fig. 10); a 10-kilohm potentiometer is used for offset nulling types CA741C, CA741, CA747CE, CA747E (See Fig. 9); and types CA1458, CA1558, CA747CT, have no specific terminals for offset nulling. Each type consists of a differential-input amplifier that effectively drives a gain and level-shifting stage having a complementary emitter-follower output.

This operational amplifier line also offers the circuit designer the option of operation with internal or external phase compensation.

Types CA748C and CA748, which are externally phase compensated (terminals 1 and 8) permit a choice of operation for improved bandwidth and slew-rate capabilities. Unity gain with external phase compensation can be obtained with a single 30-pF capacitor. All the other types are internally phase-compensated.

RCA's manufacturing process make it possible to produce IC operational amplifiers with low-burst ("popcorn") noise characteristics. Type CA6741, a low-noise version of the CA741, gives limit specifications for burst noise in the data bulletin, File No. 530. Contact your RCA Sales Representative for information pertinent to other operational amplifier types that meet low-burst noise specifications.

RCA Type No.	No. of Ampl.	Phase Comp.	Offset Voltage Null	Min. A _{OL}	Max. V _{IO} (mV)	Operating-Temperature Range (°C)
CA1458	dual	int.	no	20k	6	0 to +70 [▲]
CA1558	dual	int.	no	50k	5	-55 to +125
CA741C	single	int.	yes	20k	6	0 to +70 [▲]
CA741	single	int.	yes	50k	5	-55 to +125
CA747C	dual	int.	yes*	20k	6	0 to +70 [▲]
CA747	dual	int.	yes*	50k	5	-55 to +125
CA748C	single	ext.	yes	20k	6	0 to +70 [▲]
CA748	single	ext.	yes	50k	5	-55 to +125

*In the 14-lead dual-in-line plastic package only.

▲All types in any package style can be operated over the temperature range of -55 to +125°C, although the published limits for certain electrical specifications apply only over the temperature range of 0 to +70°C.

CA741, CA747, CA748, CA1458, CA1558 Types

ORDERING INFORMATION

When ordering any of these types, it is important that the appropriate suffix letter for the package required be affixed to the type number. For example: If a CA1458 in a straight-lead TO-5 style package is desired, order CA1458T.

TYPE NO.	PACKAGE TYPE AND SUFFIX LETTER						FIG. NO.	
	TO-5 STYLE			PLASTIC		CHIP		BEAM-LEAD
	8L	10L	DIL-CAN	8L	14L			
CA1458	T		S	E		H	1d, 1h	
CA1558	T		S	E			1d, 1h	
CA741C	T		S	E		H	1a, 1e	
CA741	T		S	E			L	
CA747C		T			E	H	1b, 1f	
CA747		T			E		1b, 1f	
CA748C	T		S	E		H	1c, 1g	
CA748	T		S	E			1c, 1g	

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$:

DC Supply Voltage (between V^+ and V^- terminals):

CA741C, CA747C[▲], CA748C, CA1458[▲] 36 V

CA741, CA747[▲], CA748, CA1558[▲] 44 V

Differential Input Voltage ± 30 V

DC Input Voltage* ± 15 V

Output Short-Circuit Duration Indefinite

Device Dissipation:

Up to 70°C (CA741C, CA748C) 500 mW

Up to 75°C (CA741, CA748) 500 mW

Up to 30°C (CA747) 800 mW

Up to 25°C (CA747C) 800 mW

Up to 30°C (CA1558) 680 mW

Up to 25°C (CA1458) 680 mW

For Temperatures Indicated Above Derate linearly $6.67\text{ mW}/^\circ\text{C}$

Voltage between Offset Null and V^- (CA741C, CA741, CA747CE) ± 0.5 V

Ambient Temperature Range:

Operating – CA741, CA747E, CA748, CA1558 -55 to $+125^\circ\text{C}$

CA741C, CA747C, CA748C, CA1458 0 to $+70^\circ\text{C}$ [†]

Storage -65 to $+150^\circ\text{C}$

Lead Temperature (During Soldering):

At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10 seconds max. 265°C

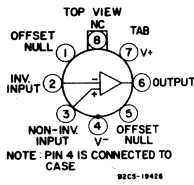
* If Supply Voltage is less than ± 15 volts, the Absolute Maximum Input Voltage is equal to the Supply Voltage.

[▲] Voltage values apply for each of the dual operational amplifiers.

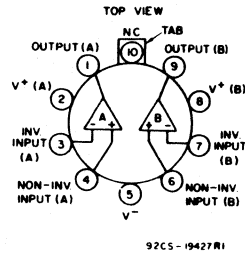
[†] All types in any package style can be operated over the temperature range of -55 to $+125^\circ\text{C}$, although the published limits for certain electrical specifications apply only over the temperature range of 0 to $+70^\circ\text{C}$.

Linear Integrated Circuits

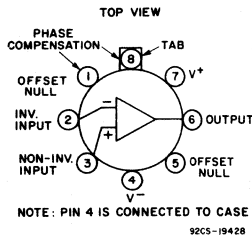
CA741, CA747, CA748, CA1458, CA1558 Types



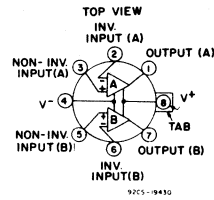
1a.—CA741CS, CA741CT, CA741S, & CA741T with internal phase compensation.



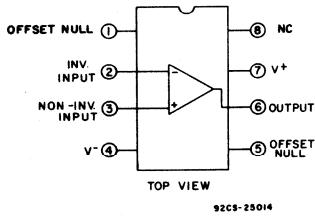
1b.—CA747CT and CA747T with internal phase compensation.



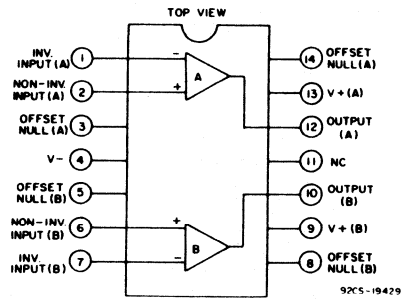
1c.—CA748CS, CA748CT, CA748S, and CA748T with external phase compensation.



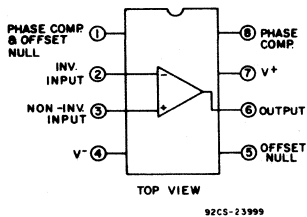
1d.—CA1458S, CA1458T, CA1558S, and CA1558T with internal phase compensation.



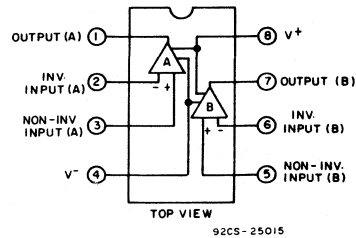
1e.—CA741C and CA741E with internal phase compensation.



1f.—CA747CE and CA747E with internal phase compensation.



1g.—CA748CE and CA748E with external phase compensation.



1h.—CA1458E and CA1558E with internal phase compensation.

Fig. 1 — Functional diagrams.

Operational Amplifiers

CA741, CA747, CA748, CA1458, CA1558 Types

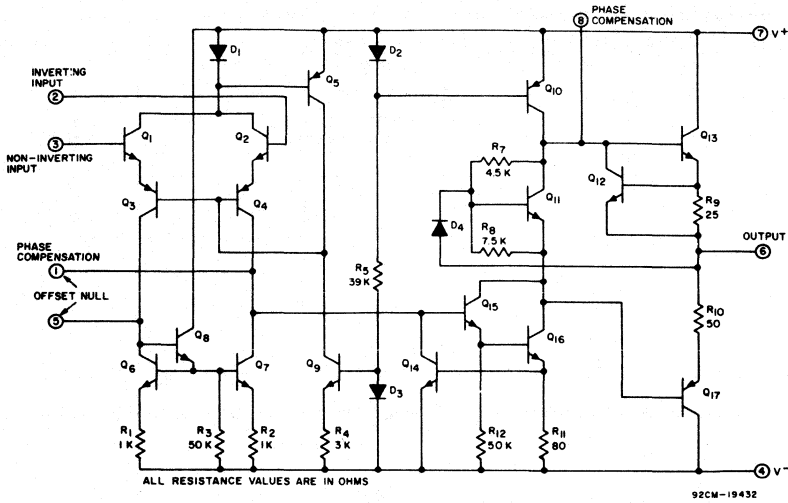


Fig.2—Schematic diagram of operational amplifier with external phase compensation for CA748C and CA748.

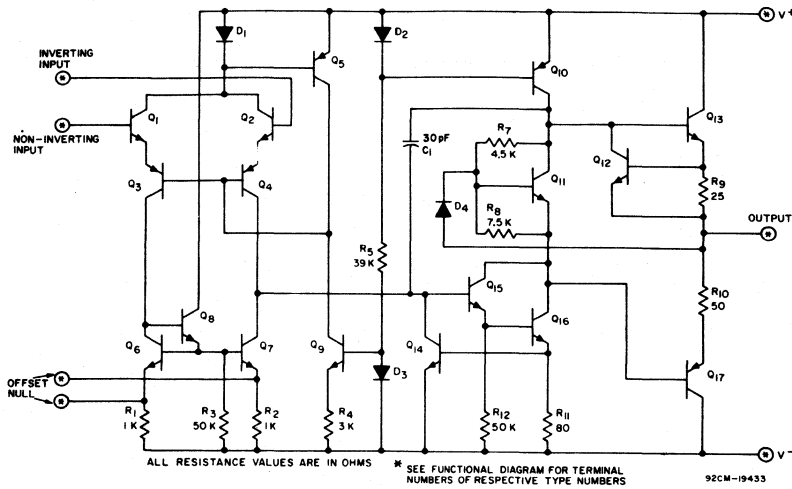


Fig.3—Schematic diagram of operational amplifiers with internal phase compensation for CA741C, CA741, and for each amplifier of the CA747C, CA747, CA1458, and CA1558.

Linear Integrated Circuits

CA741, CA747, CA748, CA1458, CA1558 Types

ELECTRICAL CHARACTERISTICS Typical Values Intended Only for Design Guidance

CHARACTERISTIC	TEST CONDITIONS $V_{\pm} = \pm 15 \text{ V}$	TYP. VALUES ALL TYPES	UNITS	
Input Capacitance, C_i		1.4	pF	
Offset Voltage Adjustment Range		± 15	mV	
Output Resistance, R_O		75	Ω	
Output Short-Circuit Current		25	mA	
Transient Response: Rise Time, t_r	Unity gain $V_I = 20 \text{ mV}$ $R_L = 2 \text{ k}\Omega$ $C_L \leq 100 \text{ pF}$	0.3	μs	
		Overshoot	5	%
Slew Rate, SR:	$R_L \geq 2 \text{ k}\Omega$	Closed-loop	0.5	V/ μs
		Open-loop [▲]	40	

▲ Open-loop slew rate applies only for types CA748C and CA748.

ELECTRICAL CHARACTERISTICS For Equipment Design

CHARACTERISTIC	TEST CONDITIONS Supply Voltage, $V^+ = 15 \text{ V}$, $V^- = -15 \text{ V}$	Ambient Temperature, T_A	LIMITS			UNITS
			CA741C CA747C* CA748C CA1458*			
			Min.	Typ.	Max.	
Input Offset Voltage, V_{IO}	$R_S \leq 10 \text{ k}\Omega$	25 °C	–	2	6	mV
		0 to 70 °C	–	–	7.5	
Input Offset Current, I_{IO}		25 °C	–	20	200	nA
		0 to 70 °C	–	–	300	
Input Bias Current, I_{IB}		25 °C	–	80	500	nA
		0 to 70 °C	–	–	800	
Input Resistance, R_i			0.3	2	–	M Ω
Open-Loop Differential Voltage Gain, A_{OL}	$R_L \geq 2 \text{ k}\Omega$ $V_O = \pm 10 \text{ V}$	25 °C	20,000	200,000	–	
		0 to 70 °C	15,000	–	–	
Common-Mode Input Voltage Range, V_{ICR}		25 °C	± 12	± 13	–	V
Common-Mode Rejection Ratio, CMRR	$R_S \leq 10 \text{ k}\Omega$	25 °C	70	90	–	dB
Supply-Voltage Rejection Ratio, PSRR	$R_S \leq 10 \text{ k}\Omega$	25 °C	–	30	150	$\mu\text{V}/\text{V}$
Output Voltage Swing, V_{OPP}	$R_L \geq 10 \text{ k}\Omega$ $R_L \geq 2 \text{ k}\Omega$	25 °C	± 12	± 14	–	V
		25 °C	± 10	± 13	–	
		0 to 70 °C	± 10	± 13	–	
Supply Current, I^{\pm}		25 °C	–	1.7	2.8	mA
Device Dissipation, P_D		25 °C	–	50	85	mW

* Values apply for each section of the dual amplifiers.

CA741, CA747, CA748, CA1458, CA1558 Types

ELECTRICAL CHARACTERISTICS
For Equipment Design

CHARACTERISTIC	TEST CONDITIONS		LIMITS			UNITS
	Supply Voltage, $V^+ = 15\text{ V}$, $V^- = -15\text{ V}$		CA741 CA747* CA748 CA1558*			
	Ambient Temperature, T_A	Min.	Typ.	Max.		
Input Offset Voltage, V_{IO}	$R_S \leq 10\text{ k}\Omega$	25 °C	—	1	5	mV
		-55 to +125 °C	—	1	6	
Input Offset Current, I_{IO}		25 °C	—	20	200	nA
		-55 °C	—	85	500	
		+125 °C	—	7	200	
Input Bias Current, I_{IB}		25 °C	—	80	500	nA
		-55 °C	—	300	1500	
		+125 °C	—	30	500	
Input Resistance, R_I			0.3	2	—	M Ω
Open-Loop Differential Voltage Gain, A_{OL}	$R_L \geq 2\text{ k}\Omega$ $V_O = \pm 10\text{ V}$	25 °C	50,000	200,000	—	
		-55 to +125 °C	25,000	—	—	
Common-Mode Input Voltage Range, V_{ICR}		-55 to +125 °C	± 12	± 13	—	V
Common-Mode Rejection Ratio, CMRR	$R_S \leq 10\text{ k}\Omega$	-55 to +125 °C	70	90	—	dB
Supply Voltage Rejection Ratio, PSRR	$R_S \leq 10\text{ k}\Omega$	-55 to +125 °C	—	30	150	$\mu\text{V/V}$
Output Voltage Swing, V_{OPP}	$R_L \geq 10\text{ k}\Omega$	-55 to +125 °C	± 12	± 14	—	V
	$R_L \geq 2\text{ k}\Omega$	-55 to +125 °C	± 10	± 13	—	
Supply Current, I^{\pm}		25 °C	—	1.7	2.8	mA
		-55 °C	—	2	3.3	
		+125 °C	—	1.5	2.5	
Device Dissipation, P_D		25 °C	—	50	85	mW
		-55 °C	—	60	100	
		+125 °C	—	45	75	

* Values apply for each section of the dual amplifiers.

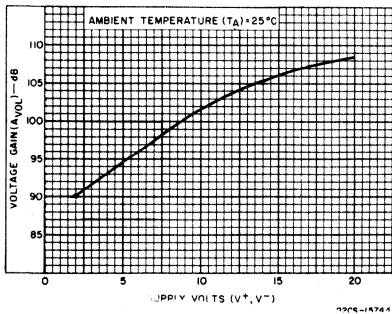


Fig. 4—Open-loop voltage gain vs. supply voltage for all types except CA748 and CA748C.

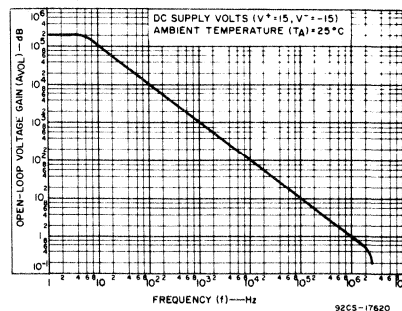


Fig. 5—Open-loop voltage gain vs. frequency for all types except CA748 and CA748C.

Linear Integrated Circuits

CA741, CA747, CA748, CA1458, CA1558 Types

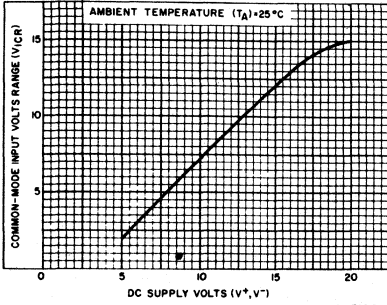


Fig.6—Common-mode input voltage range vs. supply voltage for all types.

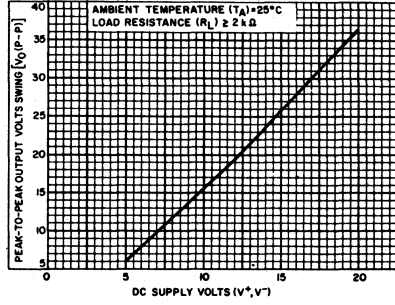


Fig.7—Peak-to-peak output voltage vs. supply voltage for all types except CA748 and CA748C.

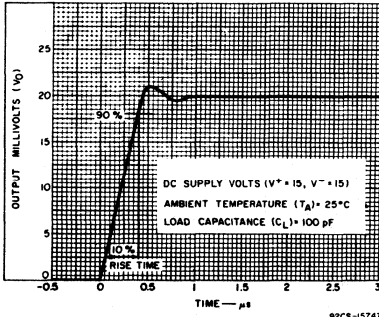


Fig.8—Output voltage vs. transient response time for CA741C and CA741.

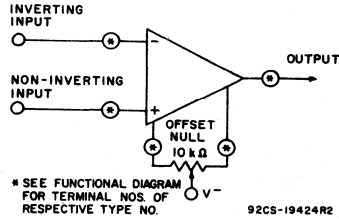


Fig.9—Voltage offset null circuit for CA741C, CA741, CA747CE, and CA747E.

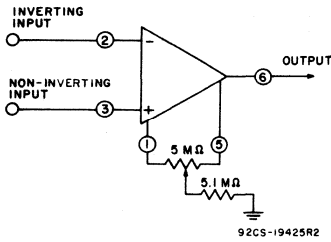


Fig.10—Voltage-offset null circuit for CA748C and CA748.

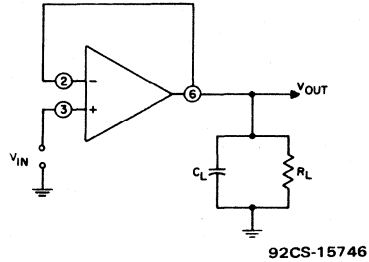


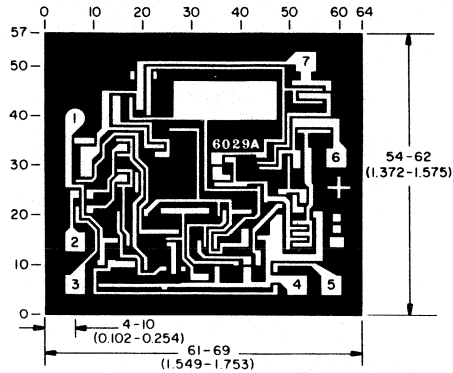
Fig.11—Transient response test circuit for all types.

CA741, CA747, CA748, CA1458, CA1558 Types

CHIP PHOTOS

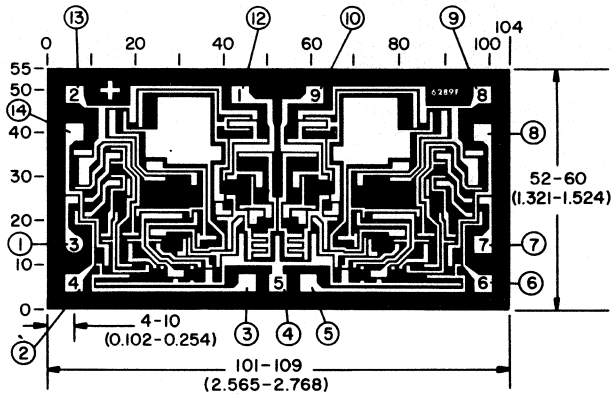
Dimensions and Pad Layouts

CA741CH



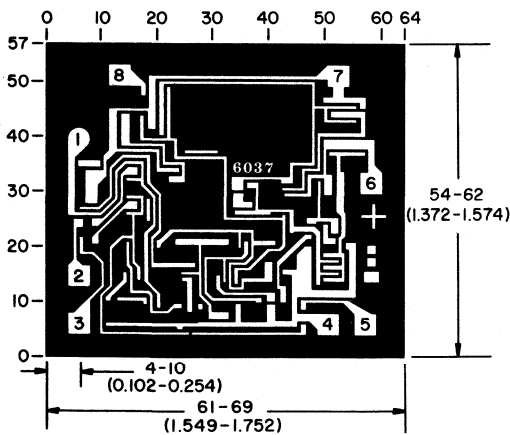
92CS-33259

CA747CH



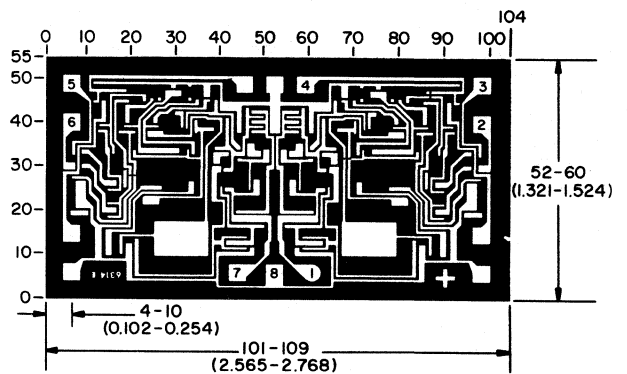
NOTE: NOS. IN PADS ARE FOR 10-LEAD TO-5
NOS. OUTSIDE OF CHIP ARE FOR 14-LEAD DIP

92CM-33260



92CS-33261

CA748CH



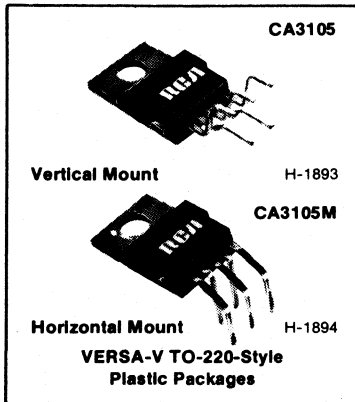
92CS-33263

CA1458H

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

CA3105, CA3105M

High-Power Operational Amplifier

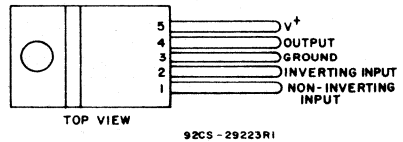


Features

- Output short circuit and thermal overload protection
- Load dump voltage surge protection
- Output current capability of up to 3.5 A
- Compensated for gains > 30
- VERSA-V power transistor package—requires no electrical insulation

The RCA-CA3105 is a monolithic silicon operational amplifier designed for driving loads as low as 1.6 ohms. It provides a high output current capability (up to 3.5 A), and rapid settling time. It is ideal for use in ac or dc servo amplifiers, deflection yoke drivers, programmable power supplies, power multivibrators, power dump flashers, etc.

The CA3105 is supplied in a 5-lead plastic TO-220-style VERSA-V package. All leads (except terminal 3) are electrically insulated from the mounting flange, eliminating the need for insulating hardware. The VERSA-V package is available with two lead configurations. The CA3105 has a vertical mount lead form, and the CA3105M has a horizontal mount lead form.



TERMINAL ASSIGNMENT

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE	28 V
OPERATING SUPPLY VOLTAGE	18 V
OUTPUT PEAK CURRENT:	
REPETITIVE	3.5 A
NON-REPETITIVE	4.5 A
POWER DISSIPATION, P_D @ $T_A=90^\circ\text{C}$	15 W
THERMAL RESISTANCE, JUNCTION-TO-CASE	4°C/W
AMBIENT-TEMPERATURE RANGE:	
OPERATING	0 to +125°C
STORAGE	-40 to +150°C
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 ± 1/32 in. (1.59 ± 0.79 mm) from case for 12 s max.	260°C

ELECTRICAL CHARACTERISTICS @ $T_A = 25^\circ\text{C}$, $V_S = +10\text{V}$ Unless Otherwise Specified

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
Input Offset Voltage, V_{IO}		—	1.3	5.0	mV
Input Bias Current, I_B	$T_A \leq T_{MAX}$	24	30	35	nA
Input Offset Current, I_{IO}	$V_{CM} = 0$	—	2.6	7	
Voltage Gain, A_{OL}		76	80	84	dB
Output Voltage Swing, V_O	$A_V = +1$ $R_L = 100\ \Omega$	± 8	± 8.5	± 8.8	V
	$R_L = 50\ \text{K}\Omega$	± 8	± 8.7	± 9	
Common Mode Rejection Ratio, CMRR		64	65	67	dB
Power Supply Rejection Ratio, PSRR		53	55	60	dB
Quiescent Supply Current, I_S		65	85	100	mA
Input Capacitance, C_{in}	$f = 1\ \text{MHz}$	—	5	—	pF
Slew Rate, SR	$R_L = 100\ \Omega$, $A_V = +1$	—	5	—	V/ μs
Gain Bandwidth Product	$A_{VL} = 0\ \text{dB}$, $R_L = 100\ \Omega$ $C_L = 100\ \text{pF}$, $V_{IN} = 20$, $f = 1\ \text{kHz}$	—	5	—	MHz

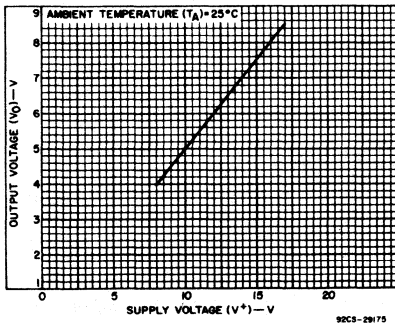


Fig. 1 - Typical quiescent output voltage as a function of supply voltage.

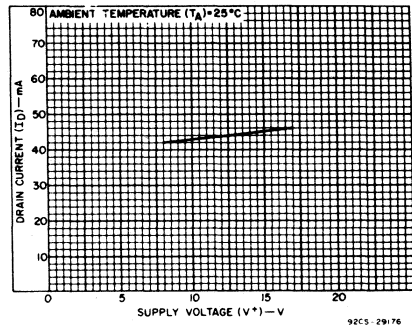


Fig. 2 - Typical quiescent drain current as a function of supply voltage.

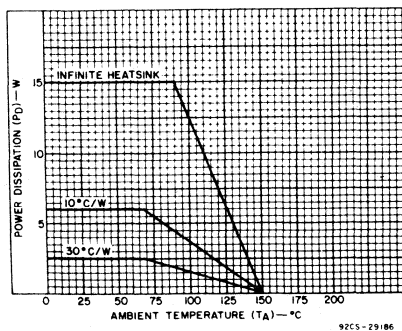


Fig. 3 - Maximum allowable power dissipation as a function of ambient temperature.

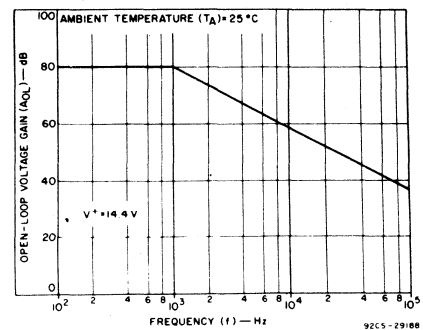
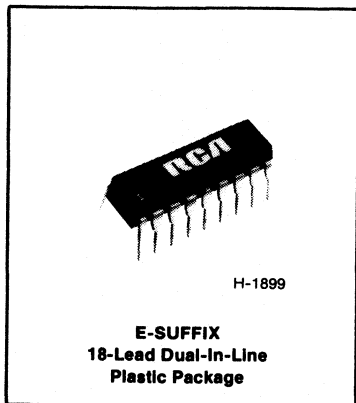


Fig. 4 - Open-loop voltage gain as a function of frequency.

CA3152E



BiMOS Input Op-Amp, Frequency Band-Select Switch, and Quad Comparator

For Television Tuning Interfacing

Features:

- Input op-amp: high impedance PMOS input transistors and internal reference bias
- Low input bias current and internal diode protection at op-amp inputs
- High op-amp output voltage swing (0.7-28.0 V dc) with 3-mA source or sink capability
- Three op-amp output voltage logic-controlled clamp levels
- Logic-controlled bandswitching with four separate outputs
- Two bandswitch output current sinks
- Two bandswitch current-limited output current sources
- Internally referenced quad comparator
- Low drive current input requirement
- Low output leakage
- High output current sink capability
- Bipolar and PMOS processes on a single chip

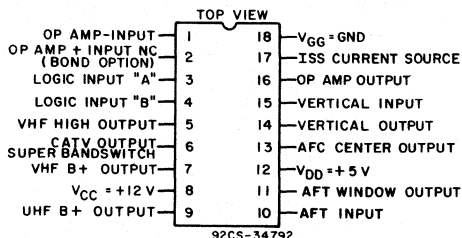
The RCA CA3152E* linear integrated circuit has three major sections for interfacing television tuning systems: an input op-amp, a band-select switch, and an internally referenced quad-comparator.

The op-amp output voltage has a wide dynamic range with a 3-mA source or sink capability and can be clamped to three discrete levels in response to logic inputs. The op-amp also has internal bias reference and phase compensation. High impedance PMOS input transistors are protected by input limiting diode clippers.

The band-select switch has two logic inputs controlling four outputs: VHF B+, VHF HIGH, SUPERBAND CATV, AND UHF B+. The VHF B+ and UHF B+ outputs are current sources which are short-circuit protected by current limiting. VHF HIGH and SUPERBAND CATV outputs are current sinks with low off-state leakage.

The quad comparator features internal reference bias, low output leakage, and 6-mA current sinking capability. The outputs of two of the comparators are internally connected to form a window comparator.

The CA3152E is supplied in an 18-lead dual-in-line plastic package.



TERMINAL ASSIGNMENT

*Formerly RCA Dev. Type No. TA10702

MAXIMUM RATINGS, Absolute-Maximum Values (T_A=25° C)

SUPPLY CURRENT (I _{SS})	20 mA
SUPPLY VOLTAGE (V _{CC}) (PIN 8)	+18 V dc
SUPPLY VOLTAGE (V _{DD}) (PIN 12)	+8 V dc
DEVICE DISSIPATION PER PACKAGE (P _D):		
UP TO 55° C	750 mW
ABOVE 55° C (Derate Linearly)	7.9 mW/° C
AMBIENT TEMPERATURE RANGE:		
OPERATING (T _A)	0 to +70 °C
STORAGE (T _{stg})	-55 to +150 °C

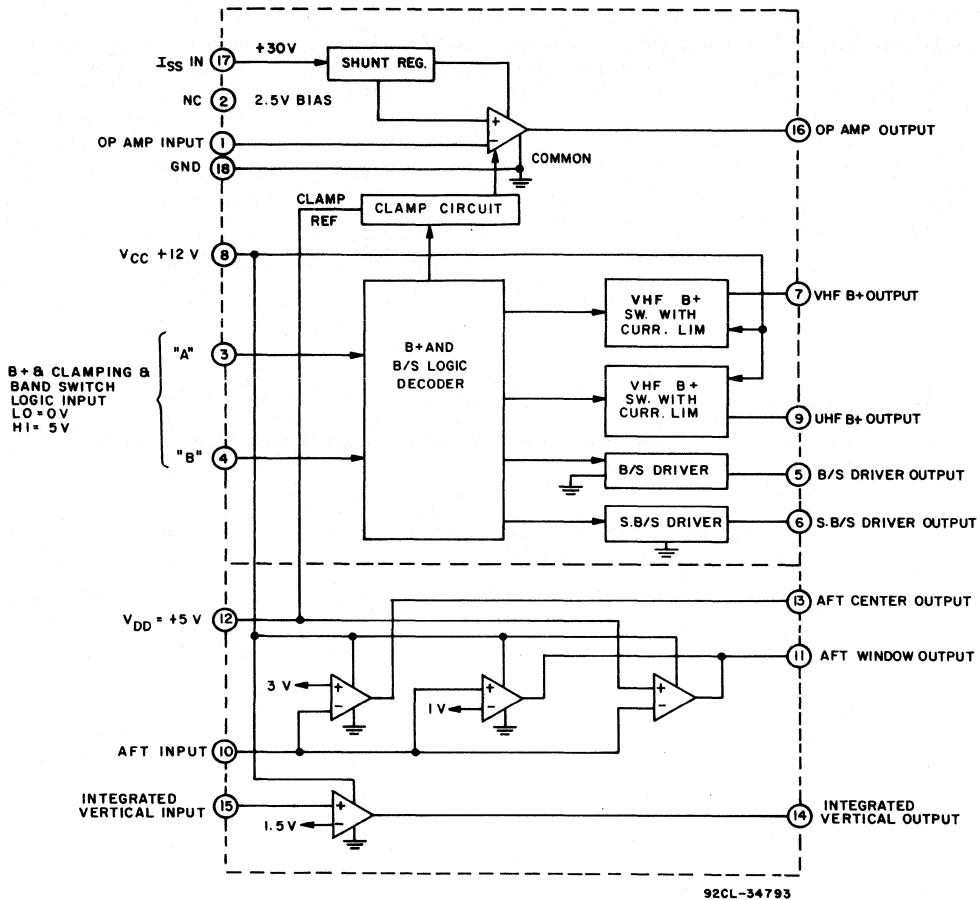


Fig. 1 - Block diagram of the CA3152E.

LOGIC TABLE FOR BANDSWITCH AND OP-AMP OUTPUTS

Inputs			BAND	Outputs				Pin 16 Voltage	
Op-Amp Pin 1	V _A Pin 3	V _B Pin 4		VHF B+ Source Pin 7	UHF B+ Source Pin 9	VHF High Sink Pin 5	Super Bandswitch CATV Sink Pin 6	Min.	Max.
1	0	0	Low VHF	ON	OFF	OFF	OFF	0.7 V	1.1 V
1	0	1	High VHF Midband CATV	ON	OFF	ON	OFF	1.6 V	2.1 V
1	1	0	Superband CATV	ON	OFF	ON	ON	4.9 V	5.75 V
1	1	1	UHF	OFF	ON	ON	OFF	0.7 V	1.1 V
0	0	0		ON	OFF	OFF	OFF	28 V	34 V
0	0	1		ON	OFF	ON	OFF	28 V	34 V
0	1	0		ON	OFF	ON	ON	28 V	34 V
0	1	1		OFF	ON	ON	OFF	28 V	34 V

Logic 1=5 V

Logic 0=0 V

Linear Integrated Circuits

CA3152E

COMMON SECTION

ELECTRICAL CHARACTERISTICS @ $T_A=25^\circ\text{C}$; $I_{SS}=9\text{ mA}$, $V_{DD}=+5\text{ V dc}$, $V_{CC}=+12\text{ V dc}$

CHARACTERISTIC	TEST CONDITIONS	LIMITS		UNITS
		Min.	Max.	
I_{CC} Supply Current, I_8	All Outputs Open	0.1	2	mA
I_{DD} Supply Current, I_{12}	All Outputs Open	0.1	1.5	mA
Tuning Voltage Supply Regulator, V_{17}	$I_{SS}=9\text{ mA}$	29	35	V dc
V_{17} Regulation, ΔV_{17}	$V_1=V_{17}$ @ $I_{SS}=6\text{ mA}$, $V_2=V_{17}$ @ $I_{SS}=12\text{ mA}$, $\Delta V_{17}= V_1-V_2 $	0	0.8	V dc

OP-AMP SECTION

ELECTRICAL CHARACTERISTICS @ $T_A=25^\circ\text{C}$; $I_{SS}=9\text{ mA}$, $V_{DD}=+5\text{ V dc}$, $V_{CC}=+12\text{ V dc}$

$V_H=2.4\text{ V Min.}$, $V_L=0.8\text{ V Max.}$, $V_A=\text{Pin 3}$, $V_B=\text{Pin 4}$

CHARACTERISTIC	V_A	V_B	TEST CONDITIONS	LIMITS		UNITS
				Min.	Max.	
Bias Voltage, V_1 Bias	V_L	V_L	Pin 1 through 10 K Ω to Pin 16	2.35	2.65	V dc
Bias Current, I_1 Bias	V_L	V_L	Pin 1 to Ground	—	100	pA
Output Source Current, I_{16} Source	V_L	V_L	$V_1=0\text{ V}$, $V_{16}=17.5\text{ V dc}$	-3	—	mA
Output Sink Current, I_{16} Sink	V_L	V_L	$V_1=5\text{ V dc}$, $V_{16}=17.5\text{ V dc}$	3	—	mA
Open Loop Voltage Gain, V_{16} AOL	V_L	V_L	$I_{SS}=10\text{ mA}$, $R_L=10\text{ K}\Omega$, $V_1=2.5\text{ V dc}$, $V_{16}=17.5\text{ V dc}$	1	—	V/mV
High Clamp Output Voltage, V_{16} HCL	V_L	V_L	$V_1=0\text{ V dc}$	28	34	V dc
Low Clamp Output Voltage, V_{16} CL1	V_L	V_L	$V_1=5\text{ V dc}$	0.7	1.1	V dc
Low Clamp Output Voltage, V_{16} CL2	V_L	V_H	$V_1=5\text{ V dc}$	1.6	2.1	V dc
Low Clamp Output Voltage, V_{16} CL3	V_H	V_L	$V_1=5\text{ V dc}$	4.9	5.75	V dc

BANDSWITCH SECTION

ELECTRICAL CHARACTERISTICS @ $T_A=25^\circ\text{C}$; $I_{SS}=9\text{ mA}$, $V_{DD}=+5\text{ V dc}$, $V_{CC}=+12\text{ V dc}$

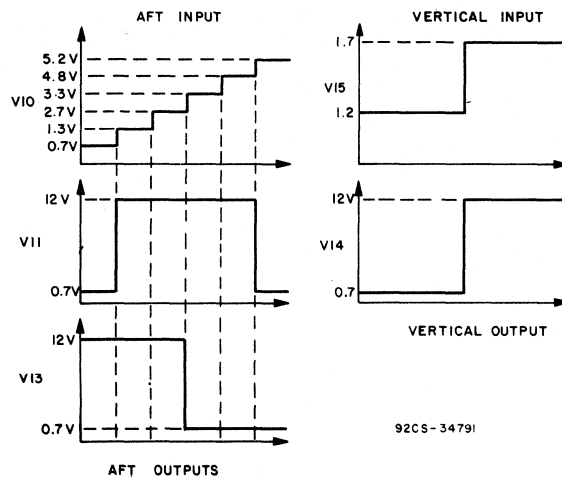
$V_H=2.4\text{ V Min.}$, $V_L=0.8\text{ V Max.}$, $V_A=\text{Pin 3}$, $V_B=\text{Pin 4}$, $V_1=5\text{ V}$

CHARACTERISTIC	V_A	V_B	TEST CONDITIONS	LIMITS		UNITS
				Min.	Max.	
Pin 7 ON (VHF ON)	V_H	V_L	$I_7=-15\text{ mA}$	11.3	—	V dc
Pin 9 ON (UHF ON)	V_H	V_H	$I_9=-15\text{ mA}$	11.3	—	V dc
Pin 7 OFF (VHF OFF)	V_H	V_H	$I_7=1\text{ mA}$	—	1.5	V dc
Pin 9 OFF (UHF OFF)	V_H	V_L	$I_9=1\text{ mA}$	—	1.5	V dc
VHF Short Circuit Current, I_7 SC	V_L	V_L	—	20	45	mA
UHF Short Circuit Current, I_9 SC	V_H	V_H	—	20	45	mA
V_5 Saturation Voltage, V_5 SAT	V_H	V_L	$I_5=2.5\text{ mA}$	—	0.5	V dc
V_6 Saturation Voltage, V_6 SAT	V_H	V_L	$I_6=2.5\text{ mA}$	—	0.5	V dc
Bandswitch Leakage Current, I_5 L	V_L	V_L	$V_5=15\text{ V dc}$	-0.2	1	μA
Superbandswitch Leakage Current, I_6 L	V_L	V_L	$V_6=15\text{ V dc}$	-0.2	1	μA
Logic Input Low Input Current, I_3 L	—	—	$V_A=0\text{ V dc}$, $V_B=5\text{ V dc}$	0	-30	μA
Logic Input Low Input Current, I_4 L	—	—	$V_A=5\text{ V dc}$, $V_B=0\text{ V dc}$	0	-30	μA
Logic Input High Input Current, I_3 H	—	—	$V_A=5\text{ V dc}$, $V_B=0\text{ V dc}$	—	1	μA
Logic Input High Input Current, I_4 H	—	—	$V_A=0\text{ V dc}$, $V_B=5\text{ V dc}$	—	1	μA

DC COMPARATOR SECTION

ELECTRICAL CHARACTERISTICS @ $T_A=25^\circ\text{C}$; $I_{SS}=9\text{ mA}$, $V_{DD}=+5\text{ V dc}$, $V_{CC}=+12\text{ V dc}$

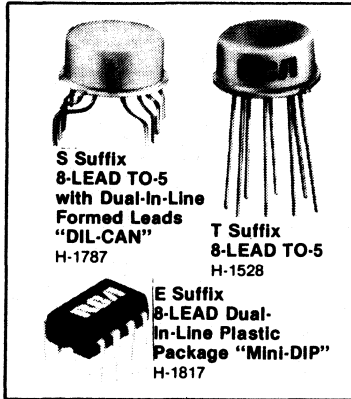
CHARACTERISTIC	TEST CONDITIONS	LIMITS		UNITS
		Min.	Max.	
Input Bias Current, I_{10} BIAS L	$V_{10}=0\text{ V dc}$	—	-750	nA
Input Bias Current, I_{10} BIAS H	$V_{10}=6\text{ V dc}$	+1	-0.450	mA
Input Bias Current, I_{15} BIAS L	$V_{15}=0\text{ V dc}$	0	-250	nA
Input Bias Current, I_{15} BIAS H	$V_{15}=6\text{ V dc}$	+1	-0.160	mA
Output Sink Current, I_{11} Sink	$V_{10}=0\text{ V dc}$, $V_{11}=1.5\text{ V dc}$	6	—	mA
Output Sink Current, I_{11} Sink	$V_{10}=6\text{ V dc}$, $V_{11}=1.5\text{ V dc}$	6	—	mA
Output Saturation Voltage, V_{11} SAT1	$V_{10}=0\text{ V dc}$, I_{11} SINK=4 mA	100	700	mV
Output Saturation Voltage, V_{11} SAT2	$V_{10}=6\text{ V dc}$, I_{11} SINK=4 mA	100	700	mV
Output Leakage Current, I_{11} LEAKAGE	$V_{10}=2.25\text{ V dc}$, $V_{11}=12\text{ V dc}$	-0.2	1.0	μA
Output Sink Current, I_{13} SINK	$V_{10}=6\text{ V dc}$, $V_{13}=1.5\text{ V dc}$	6	—	mA
Output Saturation Voltage, V_{13} SAT	$V_{10}=6\text{ V dc}$, I_{13} SINK=4 mA	100	700	mV
Output Leakage Current, I_{13} LEAKAGE	$V_{10}=2.25\text{ V dc}$, $V_{13}=12\text{ V dc}$	-0.2	1.0	μA
Output Sink Current, I_{14} SINK	$V_{15}=0\text{ V dc}$, $V_{14}=1.5\text{ V dc}$	6	—	mA
Output Saturation Voltage, V_{14} SAT	$V_{15}=0\text{ V dc}$, I_{14} SINK=4 mA	100	700	mV
Output Leakage Current, I_{14} LEAKAGE	$V_{15}=2.25\text{ V dc}$, $V_{14}=12\text{ V dc}$	-0.2	1.0	μA
AFT Center Reference Voltage, V_{13} REF	(See Fig. 2)	2.8	3.2	V dc
AFT Window Reference Voltage Low, V_{11} REF LOW	(See Fig. 2)	0.8	1.2	V dc
AFT Window Reference Voltage High, V_{11} REF HIGH	(See Fig. 2)	4.95	5.05	V dc
Vertical Output Reference, V_{14} REF	(See Fig. 2)	1.3	1.7	V dc



92CS-3479I

Fig. 2 - Quad comparator action.

CA3193, CA3193A, CA3193B Types



BIMOS Precision Operational Amplifier

FEATURES:

- Low V_{IO} : 75 μV max. (CA3193B)
200 μV max. (CA3193A)
500 μV max. (CA3193)
- Low $\Delta V_{IO}/\Delta T$: 2 $\mu\text{V}/^\circ\text{C}$ max. (CA3193B)
3 $\mu\text{V}/^\circ\text{C}$ max. (CA3193A)
5 $\mu\text{V}/^\circ\text{C}$ max. (CA3193)
- Low I_{IO} and I_I
- Low $\Delta I_{IO}/\Delta T$: 50 pA/ $^\circ\text{C}$ max. (CA3193B)
150 pA/ $^\circ\text{C}$ max. (CA3193)
0.5 nA/ $^\circ\text{C}$ max. (CA3193B)
- Low $\Delta I_I/\Delta T$: 3.7 nA/ $^\circ\text{C}$ max. (CA3193)

The CA3193B, CA3193A and CA3193 are ultra-stable, precision-instrumentation, operational amplifiers that employ both PMOS and bipolar transistors on a single monolithic chip. The CA3193-series amplifiers are internally phase-compensated and provide a gain-bandwidth product of 1.2 MHz. They are pin-compatible with the industry 741 series and many other IC op amps, and may be used as replacements for 741-series types in most applications.

The CA3193 series can also be used as functional replacements for op-amp types 725, 108A, OP-5, OP-7, LM11 and LM714 in many applications where nulling is not employed. Because of their low offset voltage and low offset voltage-versus-temperature coefficient, the CA3193-series amplifiers have a wider range of applications than most op amps and are particularly well suited for use as thermocouple amplifiers, high-gain filters, buffers, strain-gauge bridge amplifiers and precision voltage references.

The three types in the CA3193 series are functionally identical. The CA3193B, however, operates from supply voltages of ± 3.5 V to ± 22 V and has an operating temperature range of -55°C to $+125^\circ\text{C}$. The CA3193 and CA3193A operate from supply voltages of ± 3.5 V to ± 18 V and have operating temperature ranges of -25°C to $+85^\circ\text{C}$ and 0°C to $+70^\circ\text{C}$, respectively.

The CA3193-series types are supplied in standard 8-lead TO-5-style (T suffix), 8-lead dual-in-line formed lead TO-5-style (DIL-CAN—S suffix) and 8-lead dual-in-line plastic (Mini-DIP—E suffix) packages.

Circuit Description

The block diagram of the CA3193 amplifier, Fig. 2, shows the voltage gain and supply current for each of its four amplifier stages. Simplified and complete schematic diagrams of the CA3193 amplifier are shown in Figs. 3 and 4, respectively.

- Extremely high gain: 120 dB min. (CA3193B)
110 dB min. (CA3193A)
100 dB min. (CA3193)
- Low V_{IO} vs. time
- High CMRR and PSRR
- Internally compensated: 1.2-MHz gain-bandwidth product
- Low input noise: 0.1 Hz to 10 Hz
Noise voltage: 0.36 $\mu\text{Vp-p}$ typ.
Noise current: 12 pA-p typ.

APPLICATIONS

- Thermocouple preamplifiers
- Strain-gauge bridge amplifiers
- Summing amplifiers
- Differential amplifiers
- Bilateral current sources
- Log amplifiers
- Differential voltmeters
- Precision voltage references
- Active filters
- Buffers
- Integrators
- Sample-and-hold circuits
- Low frequency filters

CA3193, CA3193A, CA3193B Types

Absolute-Maximum Ratings, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

	CA3193	CA3193A	CA3193B
DC Supply Voltage	± 18	± 18	± 22 V
Differential-Mode Input Voltage	± 5	± 5	± 5 V
Common-Mode DC Input Voltage	$(V^+ - 4), V^-$	$(V^+ - 4), V^-$	$(V^+ - 4), V^-$ V
Input Terminal Current	1	1	1 mA
Device Dissipation			
Without Heat Sink			
Up to 55°C	630	630	630 mW
Above 55°C	Derate Linearly 6.67		mW/ $^\circ\text{C}$
Temperature Range	0 to 70	-25 to 85	-55 to 125 $^\circ\text{C}$
Output Short-Circuit Duration*	Indefinite	Indefinite	Indefinite
Lead Temperature (During Soldering)			
at distance of 1/16 in. \pm 1/32 in. (1.59 \pm 0.79 mm) from case for 10 seconds max.	± 265	± 265	± 265 $^\circ\text{C}$

*Short circuit may be applied to ground or to either supply.

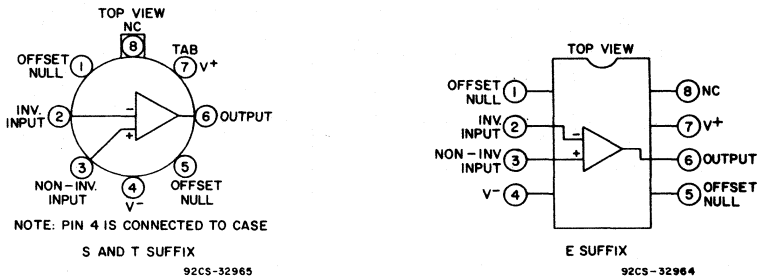


Fig. 1 — Functional diagram of CA3193 series.

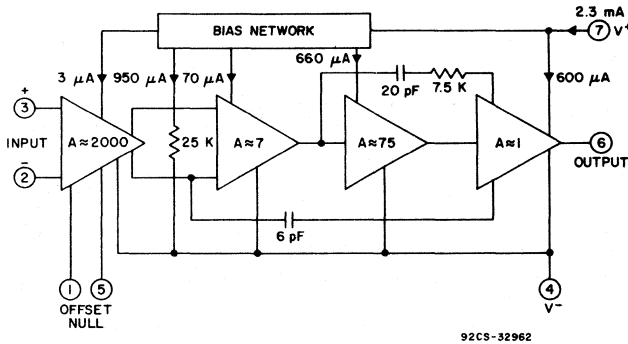


Fig. 2 — Block diagram of CA3193 series.

Circuit Description (cont'd)

A quad of physically cross-connected n-p-n transistors comprise the input-stage differential pair (Q1,Q2 in Figs. 3 and 4); this arrangement contributes to the low input offset-voltage characteristics of the amplifier. The ultra-high gain provided in the first stage ensures that subsequent stages cannot significantly influence the

overall offset-voltage characteristics of the amplifier. High load impedances for the input-stage differential pair (Q1,Q2) are provided by the cascode-connected p-n-p transistors Q3,Q5 and Q4,Q6, thereby contributing to the high gain developed in the stage.

The second stage of the amplifier consists of a differential amplifier employing PMOS/FETs (Q7,Q8 in Figs. 3 and 4) with

Linear Integrated Circuits

CA3193, CA3193A, CA3193B Types

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V^+ = 15\text{ V}$ and $V^- = 15\text{ V}$ unless otherwise specified.

CHARACTERISTIC	LIMITS									UNITS
	CA3193B			CA3193A			CA3193			
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage, $ V_{IO} $	—	40	75	—	140	200	—	300	500	μV
V_{IO} @ Max.Temp.	—	—	275	—	—	380	—	—	725	μV
Input Offset Voltage Temp. Coefficient, $\Delta V_{IO}/\Delta T$ (Over specified temperature range for each device)	—	0.60	2	—	1	3	—	1	5	$\mu\text{V}/^\circ\text{C}$
Input Offset Current, I_{IO}	—	1	3	—	3	5	—	5	10	nA
$ I_{IO} $ @ Max.Temp.	—	—	8	—	—	11	—	—	17	nA
Input Offset Current Temp. Coefficient, $\Delta I_{IO}/\Delta T$ (Over specified temperature range for each device)	—	0.01	0.05	—	0.03	0.10	—	0.04	0.15	nA/ $^\circ\text{C}$
Input Bias Current, I_I	—	6	15	—	10	20	—	20	40	nA
$ I_B $ @ Max.Temp.	—	—	60	—	—	83	—	—	207	nA
Input Bias Current Temp. Coefficient, $\Delta I_I/\Delta T$	—	0.08	0.50	—	0.10	1.18	—	0.15	3.70	nA/ $^\circ\text{C}$
Input Noise Voltage, e_n p-p (0.1 to 10 Hz)	—	0.36	0.60	—	0.36	—	—	0.36	—	$\mu\text{V p-p}$
Input Noise Voltage Density, e_n $f_o = 10\text{ Hz}$ $f_o = 100\text{ Hz}$ $f_o = 1000\text{ Hz}$ $f_o = 10\text{ kHz}$ $f_o = 100\text{ kHz}$	—	25	50	—	25	—	—	25	—	$\frac{\text{nV}}{\sqrt{\text{Hz}}}$
	—	25	45	—	25	—	—	25	—	
	—	24	45	—	24	—	—	24	—	
	—	24	45	—	24	—	—	24	—	
	—	22	40	—	22	—	—	22	—	
Input Noise Current, i_n p-p (0.1 to 10 Hz)	—	12	20	—	12	20	—	12	20	pA p-p
Input Noise Current Density, i_n $f_o = 10\text{ Hz}$ $f_o = 100\text{ Hz}$ $f_o = 1000\text{ Hz}$ $f_o = 10\text{ kHz}$ $f_o = 100\text{ kHz}$	—	0.83	2.30	—	0.83	—	—	0.83	—	$\frac{\text{pA}}{\sqrt{\text{Hz}}}$
	—	0.80	1.20	—	0.80	—	—	0.80	—	
	—	0.75	1.00	—	0.75	—	—	0.75	—	
	—	0.72	0.80	—	0.72	—	—	0.72	—	
	—	0.60	0.80	—	0.60	—	—	0.60	—	

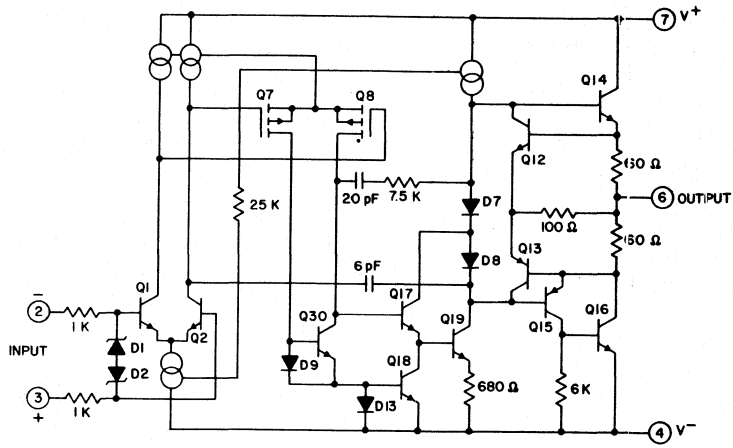
CA3193, CA3193A, CA3193B Types

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V^+ = 15\text{ V}$ and $V^- = 15\text{ V}$ (Cont'd)
unless otherwise specified.

CHARACTERISTIC	LIMITS									UNITS
	CA3193B			CA3193A			CA3193			
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Common-Mode Input Voltage Range, V_{ICR}	-12	-13.5 to 11.5	10	-12	-13.5 to 11.5	10	-12	-13.5 to 11.5	10	V
Common-Mode Rejection Ratio, ($V_{CM} = V_{ICR}$)	120	130	—	110	115	—	100	110	—	dB
		0.316	1		1.78	3.16		3.16	10	$\mu\text{V/V}$
Power Supply Rejection Ratio, PSRR, $\Delta V_{IC}/\Delta V_{\pm}$	110	130	—	100	130	—	100	130	—	dB
		0.316	3.16		0.316	10		0.316	10	$\mu\text{V/V}$
Maximum Output Voltage Swing ($R_L \geq 2\text{ K}\Omega$)	± 13.0	± 13.5	—	± 13.0	± 13.5	—	± 13.0	± 13.5	—	V
Large-Signal Voltage Gain ($V_O = \pm 10$)										
		115	—	—	—	—	—	—	—	
	$R_L \geq 1\text{ K}\Omega$	120	125	—	110	115	—	100	110	—
	$R_L \geq 2\text{ K}\Omega$	—	130	—	—	125	—	—	115	—
Short-Circuit Output Current to the Opposite Rail, I_{OM}^+ , I_{OM}^-	-25	± 7	25	-25	± 7	25	-25	± 7	25	mA
Slew Rate, SR ($R_L \geq 2\text{ K}\Omega$; Unity Gain Voltage Follower)	—	0.25	—	—	0.25	—	—	0.25	—	$\text{V}/\mu\text{s}$
Gain-Bandwidth Product, f_t $A_{OL} = 0\text{ dB}$ $R_L = 2\text{ k}\Omega$ $C_L = 100\text{ pF}$ $V_{IN} = 20$ $f = 1\text{ kHz}$	—	1.20	—	—	1.20	—	—	1.20	—	MHz
Small-Signal Transient Response, t_r ($V_{IN} = 20\text{ mV p-p}$, $f = 1\text{ kHz}$)	—	0.29	—	—	0.29	—	—	0.29	—	μs
Supply Current, $R_L = \infty$ $V^+ = 15, V^- = -15$	—	2.3	3.5	—	2.3	3.5	—	2.3	3.5	mA
Temperature Range	-55	—	125	-25	—	85	0	—	70	$^\circ\text{C}$

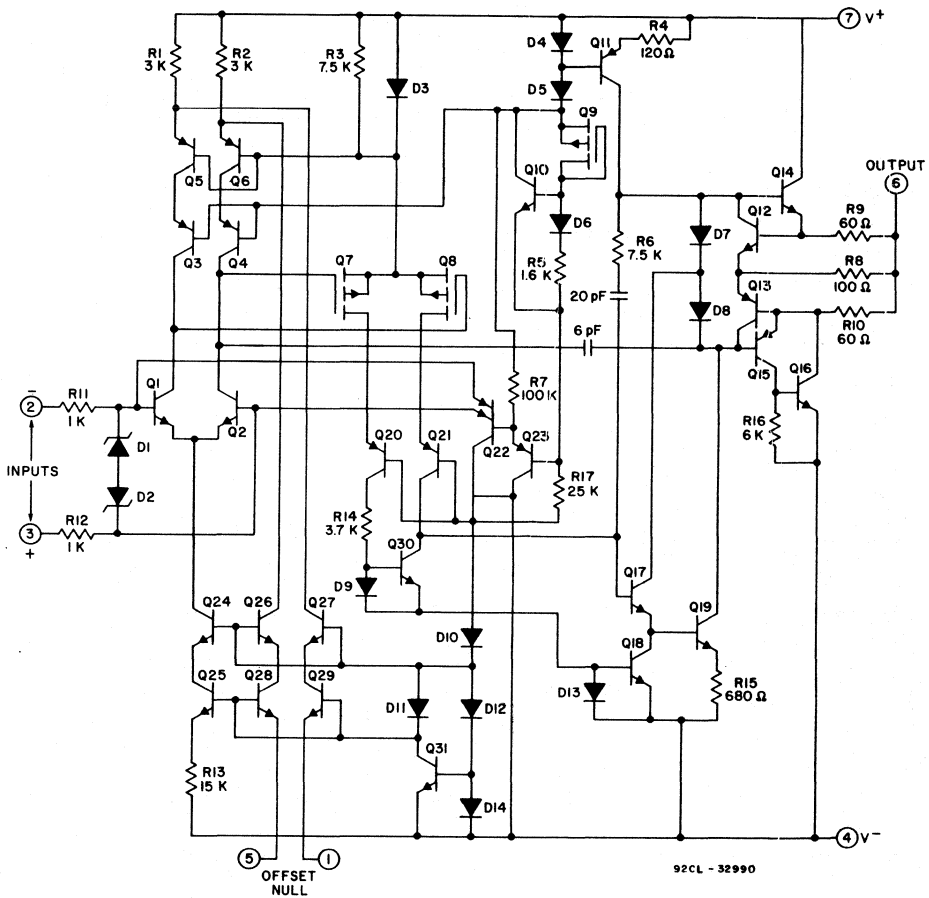
Linear Integrated Circuits

CA3193, CA3193A, CA3193B Types



92CS-32963

Fig. 3 — CA3193 simplified schematic diagram.



92CL-32990

Fig. 4 — Schematic diagram of CA3193 series.

CA3193, CA3193A, CA3193B Types

Circuit Description (cont'd)

appropriate drain loading. Since Q7 and Q8 are MOS/FETs, their loading on the first stage is quite low, thereby making an additional contribution to the high gain developed in the first stage. The second stage is also configured to convert its differential signal to a single-ended output signal by means of current mirror D9,Q30 (Figs. 3 and 4) to drive subsequent gain stage.

The third stage of the amplifier consists of Darlington-connected n-p-n transistors (Q17,Q19 in Figs. 3 and 4), driving the quasi-complementary Class AB output stage (Q14 and Q15,Q16 in Figs. 3 and 4). Output-stage short-circuit protection is activated by voltage drops developed

across the 60-ohm resistors adjacent to the output terminal (R9 and R10, Fig. 4). When the voltage drop developed across either of these resistors reaches a potential equal to $1 V_{be}$, the respective protective transistor (Q12 or Q13) is activated and shunts the base drive from the bases of the output stage transistors (Q14 and Q15,Q16).

Internal frequency compensation for the CA3193 amplifier is provided by two internal networks, a 6-pF capacitor connected between the input-stage transistor collectors and the node between the third and output stages and a second network, consisting of a 20-pF capacitor in series with a 7.5-K Ω resistor connected between the input and output nodes of the third stage.

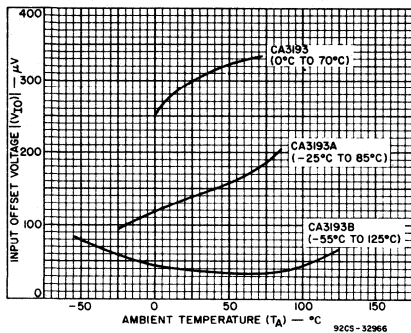


Fig. 5 — Typical input offset-voltage temperature characteristic for CA3193 series.

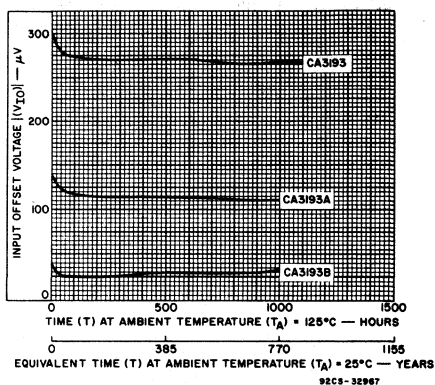


Fig. 6 — Input offset voltage vs. time.

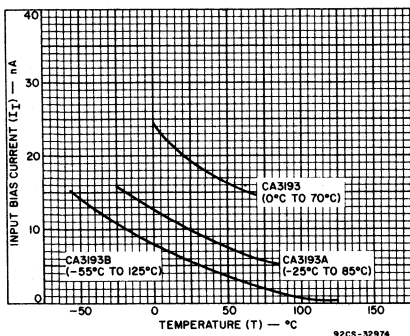


Fig. 7 — Typical input bias current vs. temperature

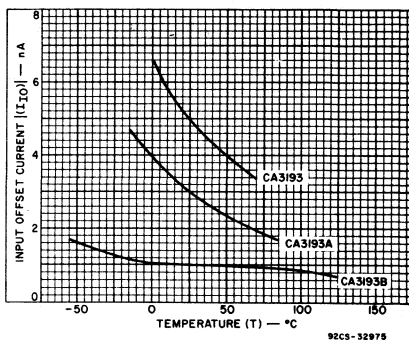


Fig. 8 — Typical input offset current vs. temperature.

Linear Integrated Circuits

CA3193, CA3193A, CA3193B Types

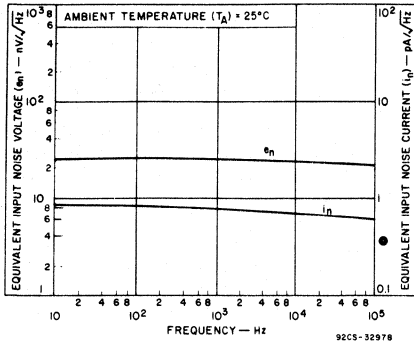


Fig. 9 — Input noise voltage and current density vs. frequency.

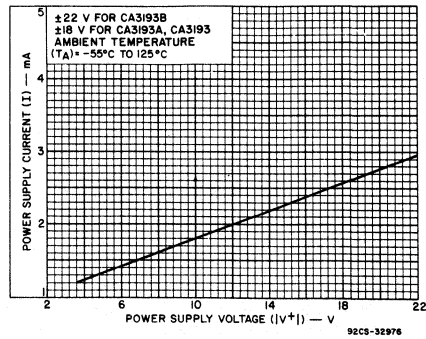


Fig. 10 — Power supply voltage (V^+ , V^-) vs. supply current.

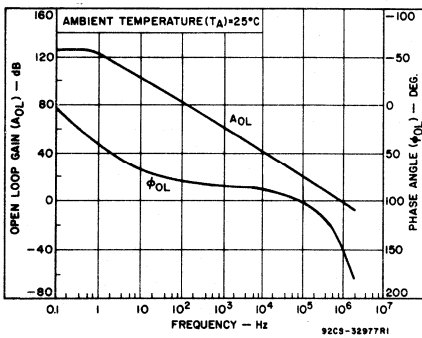


Fig. 11 — Open-loop gain and phase-shift response for CA3193B.

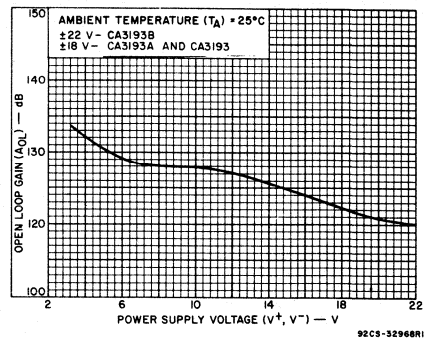


Fig. 12 — Open-loop gain vs. power-supply voltage.

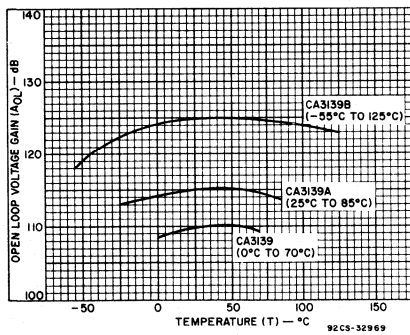


Fig. 13 — Open-loop gain vs. temperature for CA3193 series.

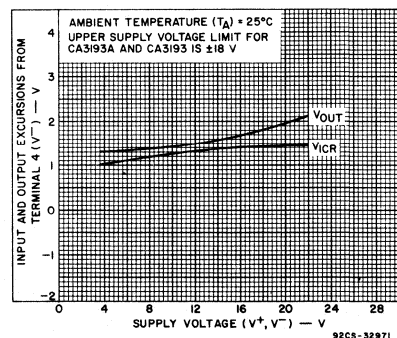


Fig. 14 — Maximum undistorted output voltage vs. frequency.

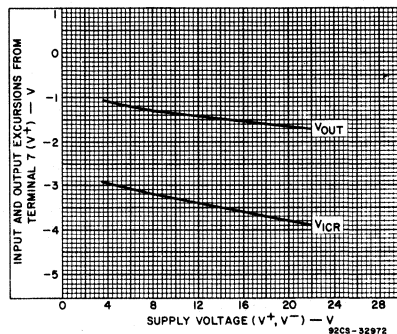


Fig. 15 — Output-voltage-swing capability and common-mode input-voltage vs. supply voltage.

Operational Amplifiers

CA3193, CA3193A, CA3193B Types

Offset Voltage Nulling

The input offset voltage can be nulled to zero by any of the three methods shown in the table below. A 10K potentiometer between terminals 1 and 5, with its wiper returned to V⁻, will provide a gross nulling for all types. For finer nulling, either of

the other two circuits shown below may be used, thus providing simpler improved resolution for all types.

CAUTION: The CA3193 amplifiers will be damaged if they are plugged into op-amp circuits employing nulling with respect to the V⁺ supply bus.

Offset Voltage Nulling

Offset Nulling Circuits			
Type	Resistor R Value	Resistor R Value	Resistor R Value
CA3193B CA3193A CA3193	10K 10K 10K	100K 50K 20K	20K 10K 5K
	Gross Offset Adjustment	Finer Offset Adjustments	

Test Circuits

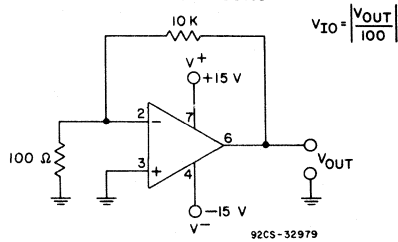
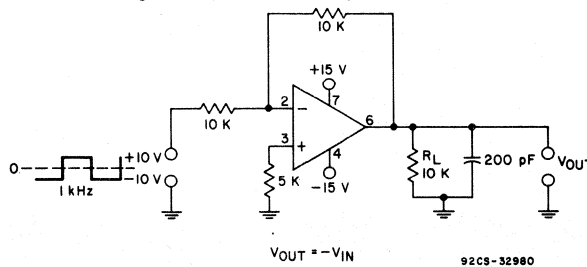
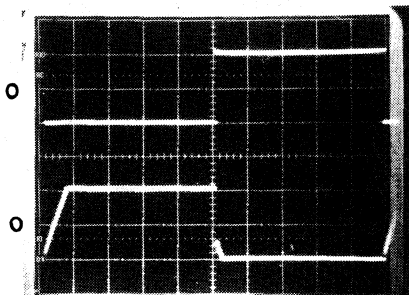


Fig. 16 - Input offset voltage test circuit.



a



b

TOP TRACE : INPUT VOLTAGE
BOTTOM TRACE : OUTPUT VOLTAGE

VERT.: $\frac{10V}{DIV}$

V⁺ = 15V
V⁻ = -15V

HOR.: $\frac{.1ms}{DIV}$

R_L = 10K

92CS-32989

Fig. 17 - Inverting amplifier (a) test circuit (b) response to 1-kHz, 20-V p-p square wave.

Linear Integrated Circuits

CA3193, CA3193A, CA3193B Types

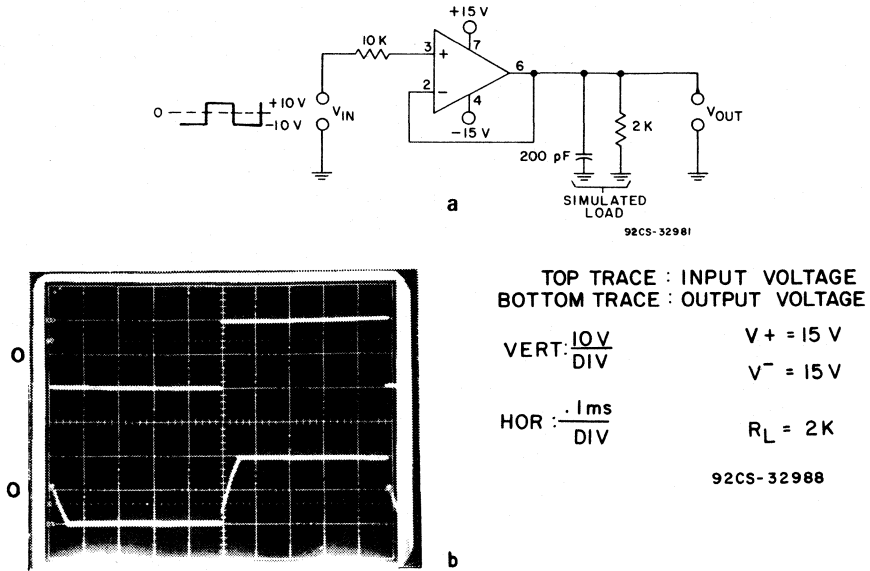


Fig. 18 - Voltage follower (a) test circuit (b) response to 20-V p-p, 1-kHz square-wave input.

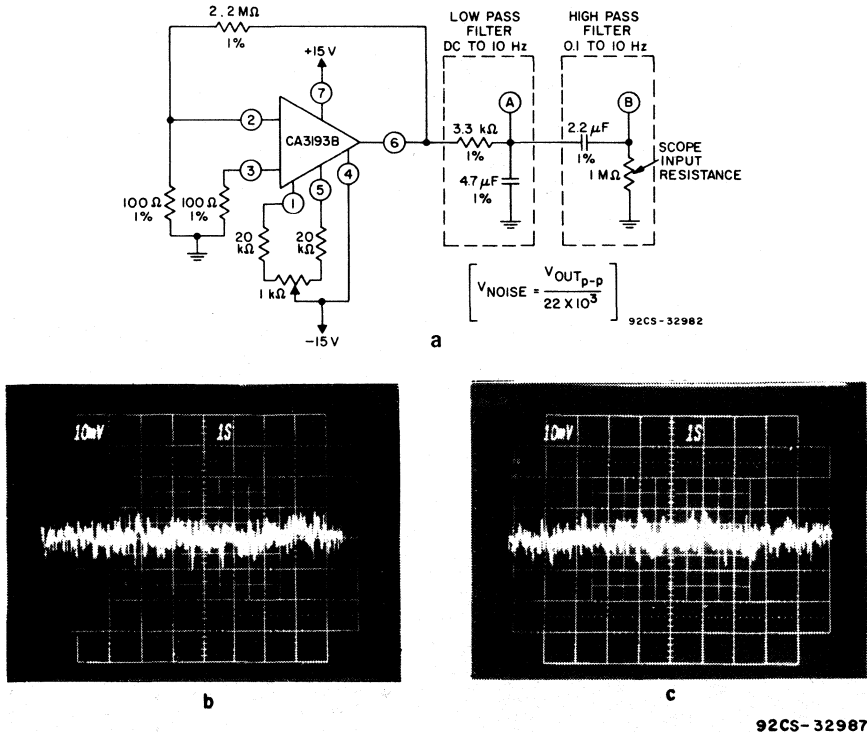
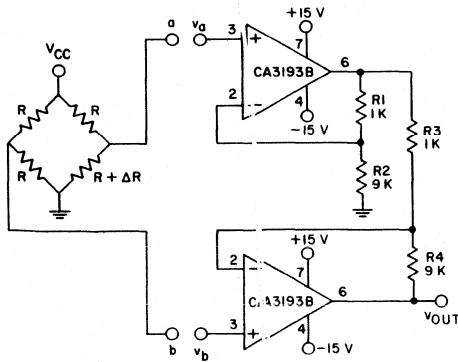


Fig. 19 - Low frequency noise (a) test circuit—0.1 to 10 Hz (b) output A waveform—0 to 10 Hz noise (c) output B waveform—0 to 10 Hz noise.

Application Circuits



$$V_{OUT} = -v_a \left(\frac{R_2}{R_1} + 1 \right) \frac{R_4}{R_3} + v_b \left(\frac{R_4}{R_3} + 1 \right)$$

FOR IDEAL RESISTORS WITH $\frac{R_1}{R_2} = \frac{R_3}{R_4}$

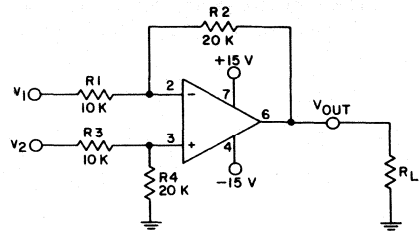
$$V_{OUT} = v_b - v_a \left(\frac{R_4}{R_3} + 1 \right)$$

$$A = \frac{V_{OUT}}{v_b - v_a} = \left(\frac{R_4}{R_3} + 1 \right)$$

FOR VALUES ABOVE $V_{OUT} = (v_b - v_a)(10)$

92CS-32984

Fig. 20 - Typical two-op amp, bridge-type differential amplifier.



$$V_{OUT} = v_2 \left(\frac{R_4}{R_3 + R_4} \right) \left(\frac{R_1 + R_2}{R_1} \right) - v_1 \left(\frac{R_2}{R_1} \right)$$

IF $R_4 = R_2, R_3 = R_1$ AND $\frac{R_2}{R_1} = \frac{R_4}{R_3}$

$$\text{THEN } V_{OUT} = (v_2 - v_1) \left(\frac{R_2}{R_1} \right)$$

FOR VALUES ABOVE $V_{OUT} \cdot 2(v_2 - v_1)$

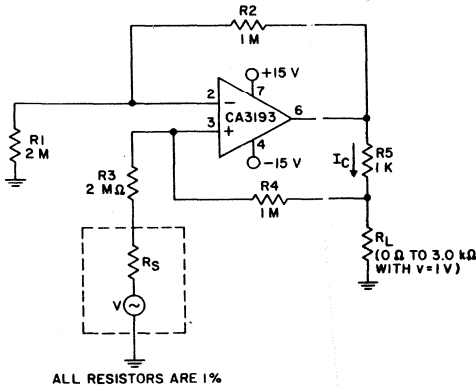
IF A_V IS TO BE MADE 1 AND IF $R_1 = R_3 = R_4 = R$ WITH $R_2 = 0.999R$ (0.1% MISMATCH IN R_2)

THEN $V_{OCM} = 0.0005 V_{IN}$ OR $CMRR = 66 \text{ dB}$

THUS, THE $CMRR$ OF THIS CIRCUIT IS LIMITED BY THE MATCHING OR MISMATCHING OF THIS NETWORK RATHER THAN THE AMPLIFIER.

92CS-32983

Fig. 21 - Differential amplifier (simple subtractor) using CA3193B.



ALL RESISTORS ARE 1%

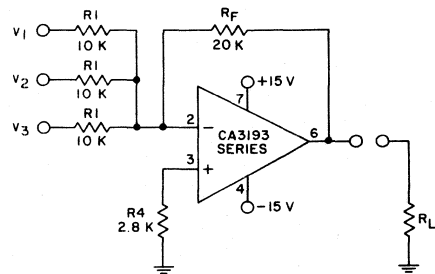
IF $R_1 = R_3$ AND $R_2 \approx R_4 + R_5$ THEN

I_L IS INDEPENDENT OF VARIATIONS IN R_L FOR R_L VALUES OF 0Ω TO $3 \text{ k}\Omega$ WITH $V = 1 \text{ V}$

$$I_L = \frac{V}{R_3} \frac{R_4}{R_5} = \frac{V}{(2 \text{ M})} \frac{1 \text{ M}}{1 \text{ K}} = \frac{V}{2 \text{ K}} = 500 \mu\text{A}$$

92CS-32985

Fig. 22 - Using CA3193B as a bilateral current source.



$$V_{OUT} = - \left(\frac{R_F}{R_1} v_1 + \frac{R_F}{R_1} v_2 + \frac{R_F}{R_1} v_3 \right)$$

$$V_{OUT} = -(2v_1 + 2v_2 + 2v_3)$$

92CS-32973

Fig. 23 - Typical summing amplifier application.

Linear Integrated Circuits

CA3193, CA3193A, CA3193B Types

The CA3193B is an excellent choice for use with thermocouples. In Fig. 24, the CA3193B amplifies the signal generated 500 times. The three 22-megohm resistors

will provide full-scale output if the thermocouple opens.

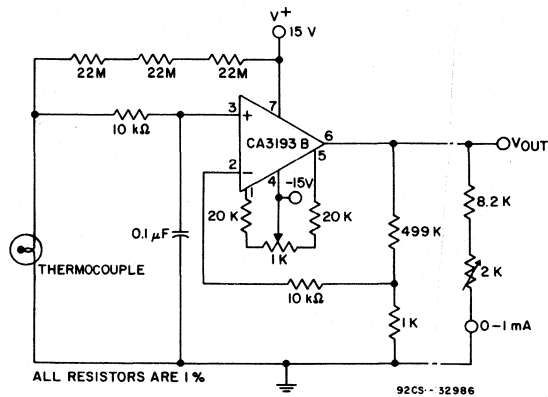
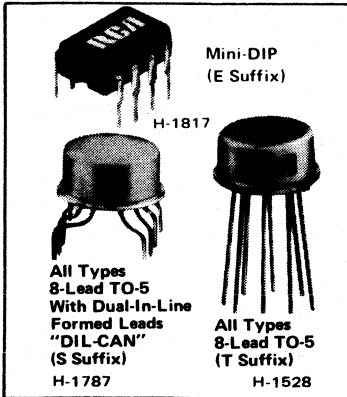


Fig. 24 - The CA3193B used in a thermocouple circuit.

Low-Supply Voltage, Low-Input Current BiMOS OP-AMPS



Features:

- 2 V Supply at 300 μ A Supply Current
- 1 pA (typ) Input Current
(Essentially Constant to 85° C)
- Rail-to-Rail Output Swing
(Drive ± 2 mA into 1 K Ω Load)
- Pin Compatible with 741 Op-Amp
- Low Cost 8-Lead Minidip, TO-5

Applications:

- pH Probe Amplifiers
- Picoammeters
- Electrometer (High Z) instruments
- Portable Equipment
- Inaccessible Field Equipment
- Battery Dependent Equipment
(Medical and Military)

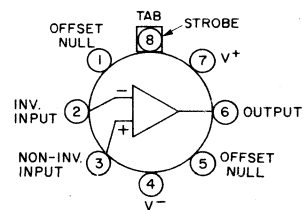
The RCA-CA3420B, CA3420A, and CA3420* are integrated-circuit operational amplifiers that combine PMOS transistors and BiPolar transistors on a single monolithic chip. The CA3420B, CA3420A, and CA3420 BiMOS operational amplifiers feature gate-protected PMOS transistors in the input circuit to provide very high input impedance, very low input currents (less than 1 pA). The internal bootstrapping network features a unique guard-banding technique for reducing the doubling of leakage current for every 10° C increase in temperature. The CA3420 series operates at total supply voltages from 2 to 20 volts either single or dual supply. These operational amplifiers are internally phase compensated to achieve stable operation in the unity gain follower configuration. Additionally, they have access terminals for a supplementary external capacitor if additional frequency roll-off is desired. Terminals are also provided for use in applications requiring input offset voltage nulling. The use of PMOS in the input stage results in common-mode input voltage capability down to 0.45 volt below the negative supply terminal, an important attribute for single-supply application. The output stage uses a feedback OTA type amplifier that can swing essentially from rail-to-rail. The output driving current of 1.5 mA MIN is provided by using non-linear current mirrors.

The CA3420-series has the same 8-lead pin-out used for the industry standard 741. They are supplied in the standard 8-lead TO-5 style package (S suffix, and T suffix); in the standard 8-lead dual-in-line plastic package (Minidip - E suffix), and are also available in chip form (H suffix).

- Formerly Dev. Type No. TA10841

TERMINAL ASSIGNMENTS

TOP VIEW

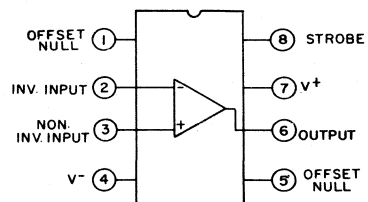


NOTE: PIN 4 IS CONNECTED TO CASE

92CS-33997

S AND T SUFFIXES

TOP VIEW



TOP VIEW

92CS-29086

E SUFFIX

Linear Integrated Circuits

CA3420, CA3420A, CA3420B

MAXIMUM RATINGS, Absolute-Maximum Values ($T_C=25^\circ\text{C}$):

DC Supply Voltage
 (Between V^+ and V^- Terminals) 22 V
 Differential-Mode
 Input Voltage ± 15 V
 Common-Mode DC
 Input Voltage ($V^+ + 8$ V) to ($V^- - 0.5$ V)
 Input-Terminal Current 1 mA
 Device Dissipation:
 Without Heat Sink —
 Up to 55°C 630 mW
 Above 55°C Derate linearly 6.67 mW/ $^\circ\text{C}$
 With Heat Sink -
 Up to 110°C 630 mW
 Above 110°C Derate linearly 16.7 mW/ $^\circ\text{C}$

Temperature Range:
 Operating (All Types) -55 to $+125^\circ\text{C}$
 Storage (All Types) -65 to $+150^\circ\text{C}$
 Output Short-Circuit
 Duration* Indefinite
 Lead Temperature
 (During Soldering):
 At Distance $1/16 \pm 1/32$ Inch
 (1.59 ± 0.79 mm) from case
 For 10 seconds max. $+265^\circ\text{C}$

*Short circuit may be applied to ground or to either supply.

TYPICAL VALUES INTENDED ONLY FOR DESIGN GUIDANCE

Characteristic	Test Conditions		CA3420B (T,S)	CA3420A (T,S,E)	CA3420 (T,S,E)	Units
	$V^+ = +10\text{V}; V^- = -10\text{V}$ $T_A = 25^\circ\text{C}$					
Input Resistance R_I			150	150	150	$\text{T}\Omega$
Input Capacitance C_I			4.9	4.9	4.9	pF
Output Resistance R_O			300	300	300	Ω
Equivalent Input Noise Voltage e_n	$f = 1$ KHz	$R_S = 100 \Omega$	62	62	62	nV/ Hz
	$f = 10$ KHz		38	38	38	
Short-Circuit Current Source Source IOM+			2.6	2.6	2.6	mA
To Opposite Supply Sink IOM-			2.4	2.4	2.4	mA
Gain-Bandwidth Product f_T			0.5	0.5	0.5	MHz
Slew Rate SR			0.5	0.5	0.5	V/ μs
Transient Response Rise Time t_r	$R_L = 2$ K Ω $C_L = 100$ pF		0.7	0.7	0.7	μs
Overshoot			15	15	15	%
Current from Terminal 8 To V^- I_{g^+}			20	20	20	μA
Current from Terminal 8 To V^+ I_{g^-}			2	2	2	mA

Operational Amplifiers

CA3420, CA3420A, CA3420B

ELECTRICAL CHARACTERISTICS FOR EQUIPMENT DESIGN

At $V_+ = 1V$, $V_- = -1V$, $T_A = 25^\circ C$ unless otherwise specified

Characteristic	Limits									Units
	CA3420B			CA3420A			CA3420			
	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage $ V_{IO} $	—	0.8	2	—	2	5	—	5	10	mV
Input Offset Current $ I_{IO} ^*$	—	0.01	4.0	—	0.01	4	—	0.01	4	pA
Input Current $ I_I ^*$	—	0.02	5	—	0.02	5	—	1	5	pA
Large-Signal Voltage Gain	20K	100K	—	20K	100K	—	10K	100K	—	V/V
AOL ($R_L = 10 K\Omega$)	86	100	—	86	100	—	80	100	—	dB
Common-Mode Rejection Ratio CMRR	—	320	560	—	560	1000	—	560	1800	$\mu V/V$
Common-Mode Input Voltage Range	+0.2	+0.5	—	+0.2	+0.5	—	+0.2	+0.5	—	V
VICR -	-1	-1.3	—	-1	-1.3	—	-1.3	—	—	V
Power Supply Rejection Ratio PSRR $\Delta V_{IO}/\Delta V$	—	20	180	—	32	320	—	100	1000	$\mu V/V$
	75	94	—	70	90	—	60	80	—	dB
Max Output Voltage VOM +	+0.90	+0.95	—	+0.90	+0.95	—	+0.90	+0.95	—	V
RL = 00 VOM -	-0.85	-0.91	—	-0.85	-0.91	—	-0.85	-0.91	—	V
Supply Current I_+	—	350	650	—	350	650	—	350	650	μA
Device Dissipation P_D	—	0.7	1.1	—	0.7	1.1	—	0.7	1.1	mW
Input Offset Voltage Temp. Drift $\Delta V_{IO}/\Delta T$	—	4	—	—	4	—	—	4	—	$\mu V/^\circ C$

ELECTRICAL CHARACTERISTICS FOR EQUIPMENT DESIGN

At $V_+ = 10V$, $V_- = -10V$, $T_A = 25^\circ C$ unless otherwise specified

Characteristic	Limits									Units
	CA3420B			CA3420A			CA3420			
	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
Input Offset Voltage $ V_{IO} $	—	0.8	2	—	2	5	—	5	10	mV
Input Offset Current $ I_{IO} ^*$	—	0.03	4	—	0.03	4	—	0.03	4	pA
Input Current $ I_I ^*$	—	0.05	5	—	0.05	5	—	0.05	5	pA
Large-Signal Voltage Gain	20K	100K	—	20K	100K	—	10K	100K	—	V/V
AQL ($R_L = 10K \Omega$)	86	100	—	86	100	—	80	100	—	dB
Common-Mode Rejection Ratio CMRR	—	32	100	—	100	320	—	100	320	$\mu V/V$
	80	90	—	70	80	—	70	80	—	dB
Common-Mode Input Voltage Range	+9.0	+9.3	—	+9.0	+9.3	—	+8.5	+9.3	—	V
VICR -	-10	-10.3	—	-10	-10.3	—	-10	-10.3	—	V
Power Supply Rejection Ratio PSRR $\Delta V_{IO}/\Delta V$	—	20	180	—	32	320	—	32	320	$\mu V/V$
	75	94	—	70	90	—	70	90	—	dB
Max Output Voltage VOM +	+9.7	+9.9	—	+9.7	+9.9	—	+9.7	+9.9	—	V
RL = 00 VOM -	-9.7	-9.85	—	-9.7	-9.85	—	-9.7	-9.85	—	V
Supply Current I_+	—	450	1000	—	450	1000	—	450	1000	μA
Device Dissipation P_D	—	9	14	—	9	14	—	9	14	mW
Input Offset Voltage Temp. Drift $\Delta V_{IO}/\Delta T$	—	4	—	—	4	—	—	4	—	$\mu V/^\circ C$

* The maximum limit represents the levels obtainable on high speed automatic test equipment. Typical values are obtained under laboratory conditions.

Linear Integrated Circuits

CA3420, CA3420A, CA3420B

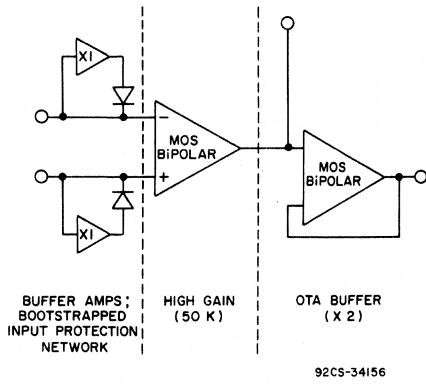


Fig. 1 - Functional diagram for CA3420.

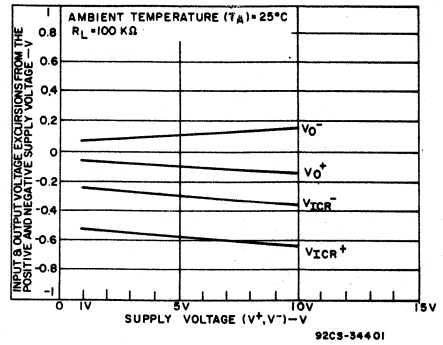


Fig. 2 - Output-voltage-swing and common-mode input-voltage range versus supply voltage.

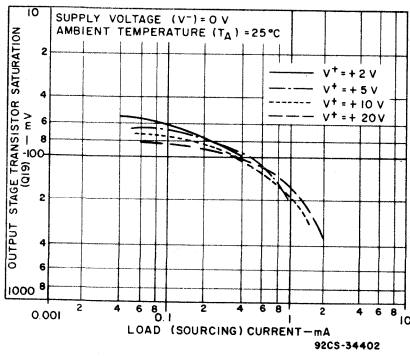


Fig. 3 - Output voltage versus load sourcing current.

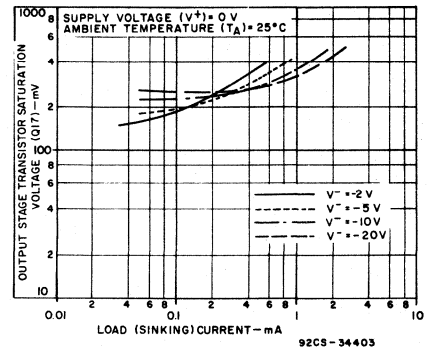


Fig. 4 - Output voltage versus load sinking current.

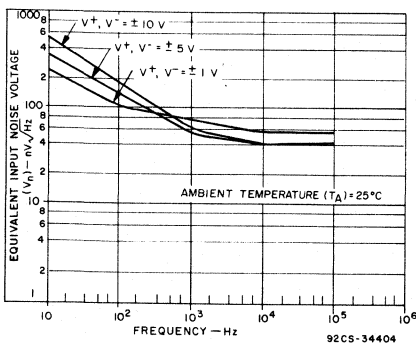


Fig. 5 - Input noise voltage versus frequency.

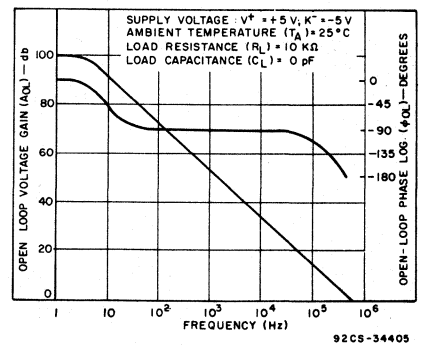


Fig. 6 - Open-loop gain and phase-shift response.

Application Circuits

Picoameter Circuit

The exceptionally low input current (typically 0.2 pA) makes the CA3420 highly suited for use in a picoameter circuit. With only a single 10K megohm resistor, this circuit covers the range from ± 1.5 pA. Higher current ranges are possible with suitable switching techniques and current scaling resistors. Input transient protection is provided by the 1-megohm resistor in series with the input. Higher current ranges require that this resistor be reduced. The 10-megohm resistor connected to pin 2 of the CA3420 decouples the potentially high input capacitance often associated with lower current circuits and reduces the tendency for the circuit to oscillate under these conditions.

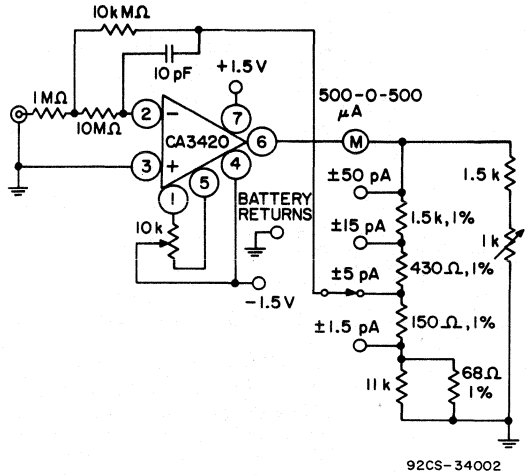


Fig. 7 - Picoameter circuit.

High-Input-Resistance Voltmeter

Advantage is taken of the high input impedance of the CA3420 in a high-input-resistance dc voltmeter. Only two 1.5 V "AA" type penlite batteries power this exceedingly high-input resistance ($>1,000,000$ -megohms) dc voltmeter. Full-scale deflection is ± 500 mV, ± 150 mV, and ± 15 mV. Higher voltage ranges are easily added with external input voltage attenuator networks.

The meter is placed in series with the gain network, thus eliminating the meter temperature coefficient error term.

Supply current in the standby position with the meter undeflected is $300 \mu\text{A}$. At full-scale deflection this current rises to $800 \mu\text{A}$. Carbon-zinc battery life should be in excess of 1,000 hours.

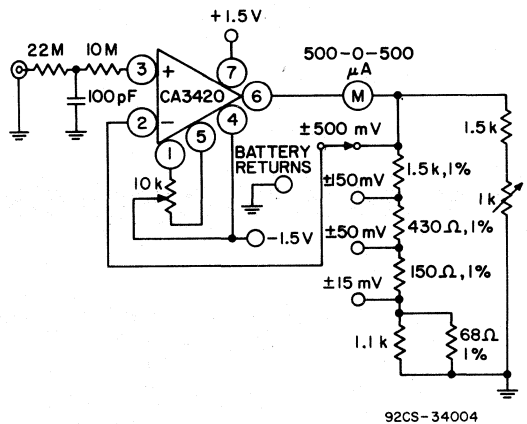
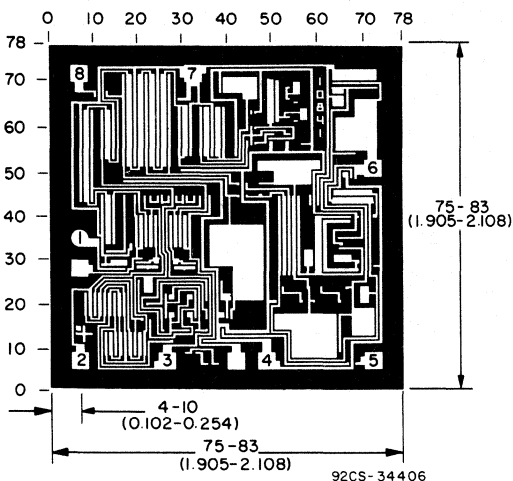


Fig. 8 - High input resistance voltmeter.

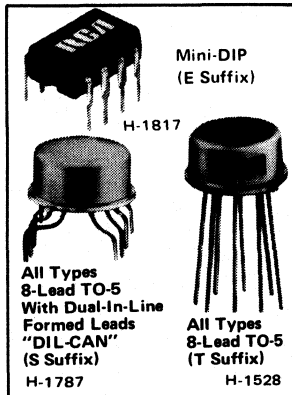


Dimensions and pad layout for CA3420H.

The layout represents a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

CA3493, CA3493A, CA3493B



BiMOS Precision Operational Amplifier

Features

- Low V_{IO} : 75 μV max. (CA3493B)
200 μV max. (CA3493A)
500 μV max. (CA3493)
- Low $\Delta V_{IO}/\Delta T$: 2 $\mu\text{V}/^\circ\text{C}$ max. (CA3493B)
3 $\mu\text{V}/^\circ\text{C}$ max. (CA3493A)
5 $\mu\text{V}/^\circ\text{C}$ max. (CA3493)
- Low I_{IO} and I_I
- Low $\Delta I_{IO}/\Delta T$: 50 $\text{pA}/^\circ\text{C}$ max. (CA3493B)
150 $\text{pA}/^\circ\text{C}$ max. (CA3493)
- Low $\Delta I_I/\Delta T$: 0.5 $\text{nA}/^\circ\text{C}$ max. (CA3493B)
3.7 $\text{nA}/^\circ\text{C}$ max. (CA3493)

The CA3493B, CA3493A and CA3493 are ultra-stable, precision-instrumentation, operational amplifiers that employ both PMOS and bipolar transistors on a single monolithic chip. The CA3493-series amplifiers are internally phase-compensated and provide a gain-bandwidth product of 1.2 MHz. They are pin-compatible with many industrial types such as 725, 108A, OP-5, OP-7, LM11 and LM714 where positive nulling is employed.

Because of their low offset voltage and low offset voltage-versus-temperature coefficient, the CA3493-series amplifiers have a wider range of applications than most op amps and are particularly well suited for use as thermocouple amplifiers, high-gain filters, buffers, strain-gauge bridge amplifiers and precision voltage references.

The three types in the CA3493 series are functionally identical. The CA3493B, however, operates from supply voltages of ± 3.5 V to ± 22 V and has an operating temperature range of -55°C to $+125^\circ\text{C}$. The CA3493 and CA3493A operate from supply voltages of ± 3.5 V to ± 18 V and have operating temperature ranges of -25°C to $+85^\circ\text{C}$ and 0°C to $+70^\circ\text{C}$, respectively.

The CA3493-series types are supplied in standard 8-lead TO-5-style (T suffix), 8-lead dual-in-line formed lead TO-5-style

- Extremely high gain:
120 dB min. (CA3493B)
110 dB min. (CA3493A)
100 dB min. (CA3493)
- Low V_{IO} vs. time
- High CMRR and PSRR
- Internally compensated: 1.2-MHz gain-bandwidth product
- Low input noise: 0.1 Hz to 10 Hz
Noise voltage: 0.36 μV_{p-p} typ.
Noise current: 12 pA_{p-p} typ.

Applications

- Thermocouple preamplifiers
- Strain-gauge bridge amplifiers
- Summing amplifiers
- Differential amplifiers
- Bilateral current sources
- Log amplifiers
- Differential voltmeters
- Precision voltage references
- Active filters
- Buffers
- Integrators
- Sample-and-hold circuits
- Low frequency filters

(DIL-CAN—S suffix) and 8-lead dual-in-line plastic (Mini-DIP—E suffix) packages.

Circuit Description

The block diagram of the CA3493 amplifier, Fig. 2, shows the voltage gain and supply current for each of its four amplifier stages. Simplified and complete schematic diagrams of the CA3493 amplifier are shown in Figs. 3 and 4, respectively.

CA3493, CA3493A, CA3493B

Absolute-Maximum Ratings, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

	CA3493B	CA3493A	CA3493
DC Supply Voltage	± 22	± 18	± 18 V
Differential-Mode Input Voltage	± 5	± 5	± 5 V
Common-Mode DC Input Voltage	$(V+ -4), V-$	$(V+ -4), V-$	$(V+ -4), V-$ V
Input Terminal Current	1	1	1 mA
Device Dissipation			
Without Heat Sink			
Up to 55°C	630	630	630 mW
Above 55°C		Derate Linearly 6.67	mW/ $^\circ\text{C}$
Temperature Range	-55 to 125	-25 to 85	0 to 70°C
Output Short-Circuit Duration*	Indefinite	Indefinite	Indefinite
Lead Temperature (During Soldering)			
at distance of 1/16 in. \pm 1/32 in. (1.59 \pm 0.79 mm) from case for 10 seconds max.			
	± 265	± 265	$\pm 265^\circ\text{C}$

*Short circuit may be applied to ground or to either supply.

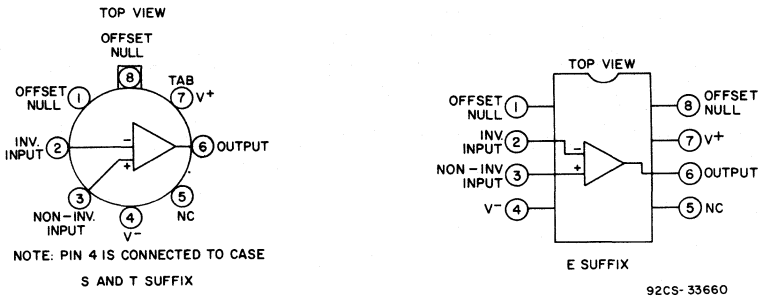


Fig. 1 - Functional diagram of CA3493 series.

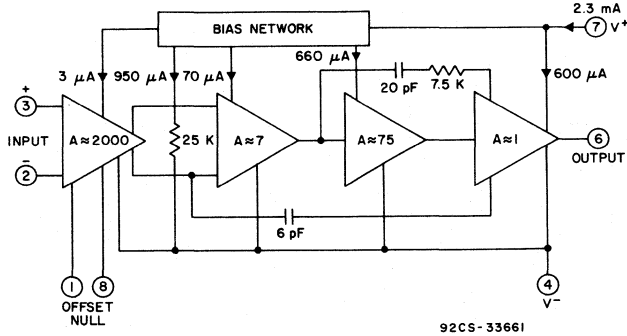


Fig. 2 - Block diagram of CA3493 series.

Circuit Description (cont'd)

A quad of physically cross-connected n-p-n transistors comprise the input-stage differential pair (Q1,Q2 in Figs. 3 and 4); this arrangement contributes to the low input offset-voltage characteristics of the amplifier. The ultra-high gain provided in the first stage ensures that subsequent stages cannot significantly influence the

overall offset-voltage characteristics of the amplifier. High load impedances for the input-stage differential pair (Q1,Q2) are provided by the cascode-connected p-n-p transistors Q3,Q5 and Q4,Q6, thereby contributing to the high gain developed in the stage.

The second stage of the amplifier consists of a differential amplifier employing PMOS/FETs (Q7,Q8 in Figs. 3 and 4) with

Linear Integrated Circuits

CA3493, CA3493A, CA3493B

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V^+ = 15\text{ V}$ and $V^- = 15\text{ V}$
unless otherwise specified.

CHARACTERISTIC	LIMITS									UNITS
	CA3493B			CA3493A			CA3493			
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage, $ V_{IO} $	—	40	75	—	140	200	—	300	500	μV
V_{IO} @ Max.Temp.	—	—	275	—	—	380	—	—	725	μV
Input Offset Voltage Temp. Coefficient, $\Delta V_{IO}/\Delta T$ (Over specified temperature range for each device)	—	0.60	2	—	1	3	—	1	5	$\mu\text{V}/^\circ\text{C}$
Input Offset Current, I_{IO}	—	1	3	—	3	5	—	5	10	nA
$ I_{IO} $ @ Max.Temp.	—	—	8	—	—	11	—	—	17	nA
Input Offset Current Temp. Coefficient, $\Delta I_{IO}/\Delta T$ (Over specified temperature range for each device)	—	0.01	0.05	—	0.03	0.10	—	0.04	0.15	nA/ $^\circ\text{C}$
Input Bias Current, I_I	—	6	15	—	10	20	—	20	40	nA
$ I_I $ @ Max.Temp.	—	—	60	—	—	83	—	—	207	nA
Input Bias Current Temp. Coefficient, $\Delta I_I/\Delta T$	—	0.08	0.50	—	0.10	1.18	—	0.15	3.70	nA/ $^\circ\text{C}$
Input Noise Voltage, e_n p-p (0.1 to 10 Hz)	—	0.36	0.60	—	0.36	—	—	0.36	—	$\mu\text{V p-p}$
Input Noise Voltage Density, e_n $f_o = 10\text{ Hz}$ $f_o = 100\text{ Hz}$ $f_o = 1000\text{ Hz}$ $f_o = 10\text{ kHz}$ $f_o = 100\text{ kHz}$	—	25	50	—	25	—	—	25	—	$\frac{\text{nV}}{\sqrt{\text{Hz}}}$
	—	25	45	—	25	—	—	25	—	
	—	24	45	—	24	—	—	24	—	
	—	24	45	—	24	—	—	24	—	
	—	22	40	—	22	—	—	22	—	
Input Noise Current, i_n p-p (0.1 to 10 Hz)	—	12	20	—	12	20	—	12	20	pA p-p
Input Noise Current Density, i_n $f_o = 10\text{ Hz}$ $f_o = 100\text{ Hz}$ $f_o = 1000\text{ Hz}$ $f_o = 10\text{ kHz}$ $f_o = 100\text{ kHz}$	—	0.83	2.30	—	0.83	—	—	0.83	—	$\frac{\text{pA}}{\sqrt{\text{Hz}}}$
	—	0.80	1.20	—	0.80	—	—	0.80	—	
	—	0.75	1.00	—	0.75	—	—	0.75	—	
	—	0.72	0.80	—	0.72	—	—	0.72	—	
	—	0.60	0.80	—	0.60	—	—	0.60	—	

Operational Amplifiers

CA3493, CA3493A, CA3493B

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V^+ = 15\text{ V}$ and $V^- = -15\text{ V}$ (Cont'd)
 unless otherwise specified.

CHARACTERISTIC	LIMITS									UNITS
	CA3493B			CA3493A			CA3493			
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Common-Mode Input Voltage Range, V_{ICR}	-12	-13.5 to 11.5	10	-12	-13.5 to 11.5	10	-12	-13.5 to 11.5	10	V
Common-Mode Rejection Ratio, $(V_{CM} = V_{ICR})$	120	130	—	110	115	—	100	110	—	dB
		0.316	1		1.78	3.16		3.16	10	$\mu\text{V/V}$
Power Supply Rejection Ratio, PSRR, $\Delta V_{IO}/\Delta V \pm$	110	130	—	100	130	—	100	130	—	dB
		0.316	3.16		0.316	10		0.316	10	$\mu\text{V/V}$
Maximum Output Voltage Swing ($R_L \geq 2\text{ K}\Omega$)	± 13.0	± 13.5	—	± 13.0	± 13.5	—	± 13.0	± 13.5	—	V
Large-Signal Voltage Gain ($V_O = \pm 10$) $R_L \geq 1\text{ K}\Omega$ $R_L \geq 2\text{ K}\Omega$ $R_L \geq 10\text{ K}\Omega$	—	115	—	—	—	—	—	—	—	dB
	120	125	—	110	115	—	100	110	—	
	—	130	—	—	125	—	—	115	—	
	—	—	—	—	—	—	—	—	—	
Short-Circuit Output Current to the Opposite Rail, I_{OM}^+ , I_{OM}^-	-25	± 7	25	-25	± 7	25	-25	± 7	25	mA
Slew Rate, SR ($R_L \geq 2\text{ K}\Omega$; Unity Gain Voltage Follower)	—	0.25	—	—	0.25	—	—	0.25	—	$\text{V}/\mu\text{s}$
Gain-Bandwidth Product, f_t $A_{OL} = 0\text{ dB}$ $R_L = 2\text{ k}\Omega$ $C_L = 100\text{ pF}$ $V_{IN} = 20$ $f = 1\text{ kHz}$	—	1.20	—	—	1.20	—	—	1.20	—	MHz
Small-Signal Transient Response, t_r ($V_{IN} = 20\text{ mV p-p}$, $\bar{f} = 1\text{ kHz}$)	—	0.29	—	—	0.29	—	—	0.29	—	μs
Supply Current, $R_L = \infty$ $V^+ = 15$, $V^- = -15$	—	2.3	3.5	—	2.3	3.5	—	2.3	3.5	mA
Temperature Range	-55	—	125	-25	—	85	0	—	70	$^\circ\text{C}$

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CA3493, CA3493A, CA3493B

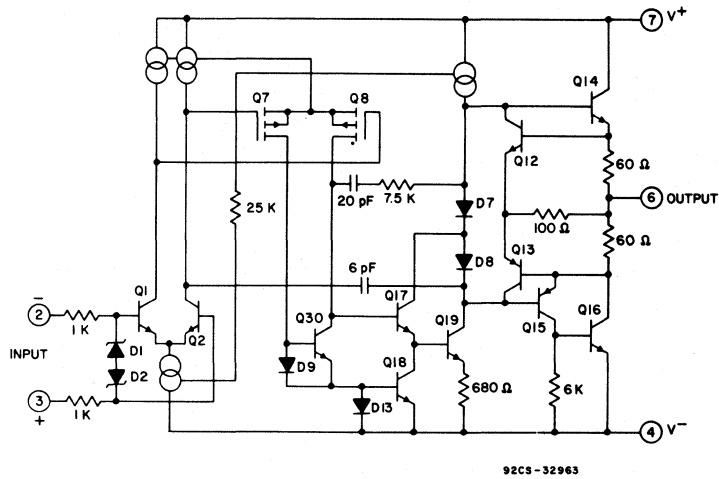


Fig. 3 - CA3493 simplified schematic diagram.

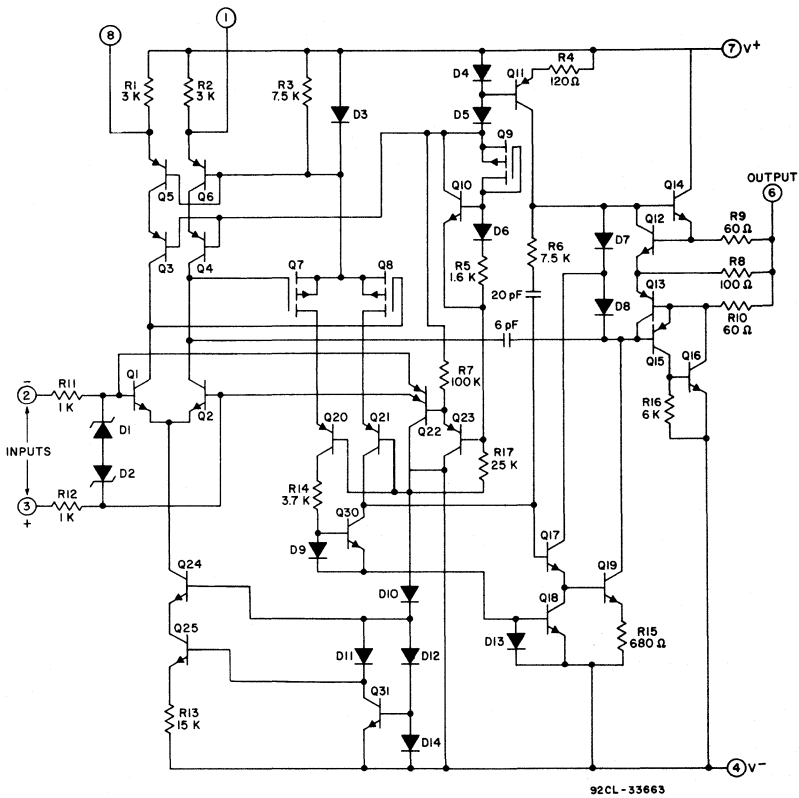


Fig. 4 - Schematic diagram of CA3493 series.

CA3493, CA3493A, CA3493B

Circuit Description (cont'd)

appropriate drain loading. Since Q7 and Q8 are MOS/FETs, their loading on the first stage is quite low, thereby making an additional contribution to the high gain developed in the first stage. The second stage is also configured to convert its differential signal to a single-ended output signal by means of current mirror D9, Q30 (Figs. 3 and 4) to drive subsequent gain stage.

The third stage of the amplifier consists of Darlington-connected n-p-n transistors (Q17, Q19 in Figs. 3 and 4), driving the quasi-complementary Class AB output stage (Q14 and Q15, Q16 in Figs. 3 and 4). Output-stage short-circuit protection is activated by voltage drops developed

across the 60-ohm resistors adjacent to the output terminal (R9 and R10, Fig. 4). When the voltage drop developed across either of these resistors reaches a potential equal to $1 V_{BE}$, the respective protective transistor (Q12 or Q13) is activated and shunts the base drive from the bases of the output stage transistors (Q14 and Q15, Q16).

Internal frequency compensation for the CA3493 amplifier is provided by two internal networks, a 6-pF capacitor connected between the input-stage transistor collectors and the node between the third and output stages and a second network, consisting of a 20-pF capacitor in series with a 7.5-K Ω resistor connected between the input and output nodes of the third stage.

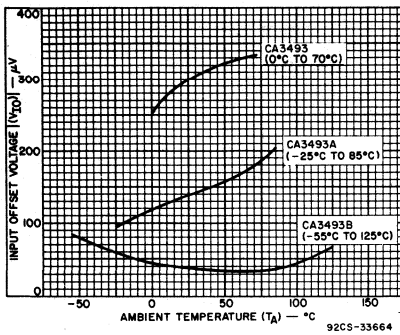


Fig. 5 — Typical input offset-voltage temperature characteristic for CA3493 series.

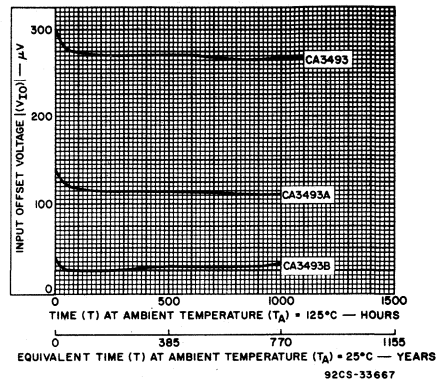


Fig. 6 — Input offset voltage vs. time.

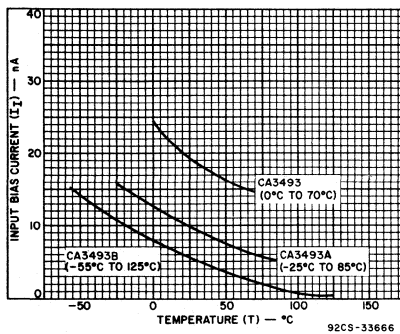


Fig. 7 — Typical input bias current vs. temperature

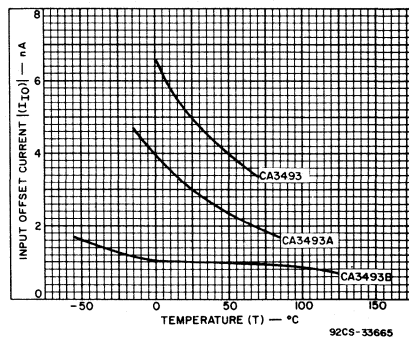


Fig. 8 — Typical input offset current vs. temperature.

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CA3493, CA3493A, CA3493B

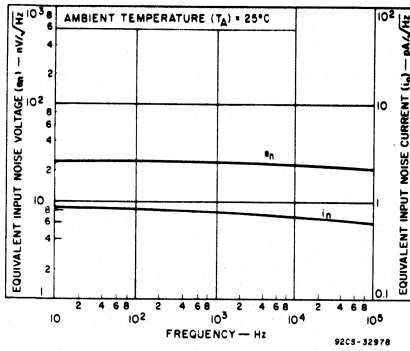


Fig. 9 — Input noise voltage and current density vs. frequency.

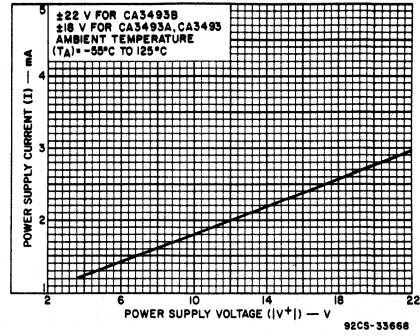


Fig. 10 — Power supply voltage (V^+ , V^-) vs. supply current.

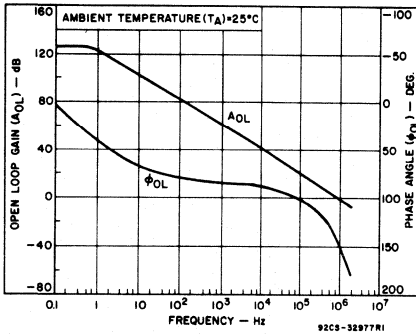


Fig. 11 — Open-loop gain and phase-shift response for CA3493B.

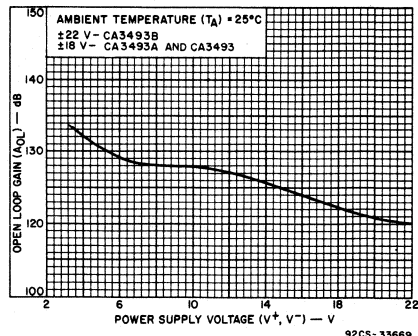


Fig. 12 — Open-loop gain vs. power-supply voltage.

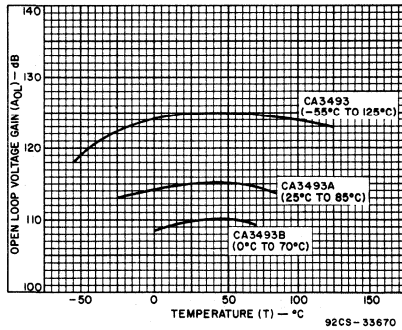


Fig. 13 — Open-loop gain vs. temperature for CA3493 series.

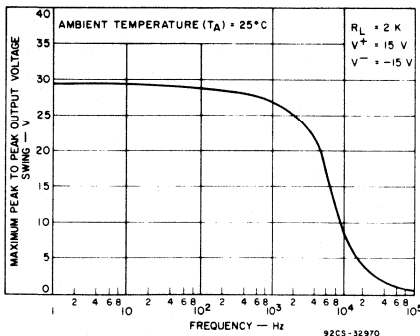


Fig. 14 — Maximum undistorted output voltage vs. frequency.

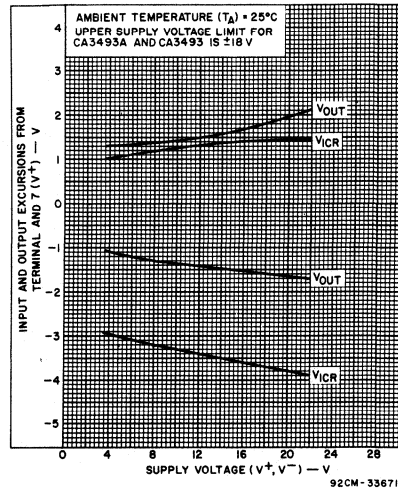


Fig. 15 — Output-voltage-swing capability and common-mode input-voltage vs. supply voltage.

CA3493, CA3493A, CA3493B


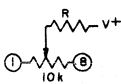
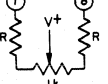
Offset Voltage Nulling

The input offset voltage can be nulled to zero by any of the three methods shown in the table below. A 10K potentiometer between terminals 1 and 8, with its wiper returned to V⁺, will provide a gross nulling for all types. For finer nulling, either of

the other two circuits shown below may be used, thus providing simpler improved resolution for all types.

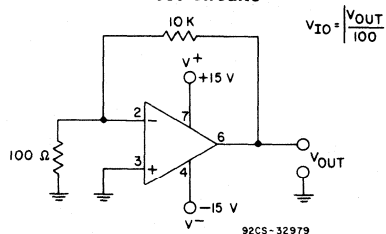
CAUTION: The CA3493 amplifiers will be damaged if they are plugged into op-amp circuits employing nulling with respect to the V⁻ supply bus.

Offset Voltage Nulling

Offset Nulling Circuits			
Type	Resistor R Value	Resistor R Value	Resistor R Value
CA3493B	10K	100K	20K
CA3493A	10K	50K	10K
CA3493	10K	20K	5K
	Gross Offset Adjustment	Finer Offset Adjustments	

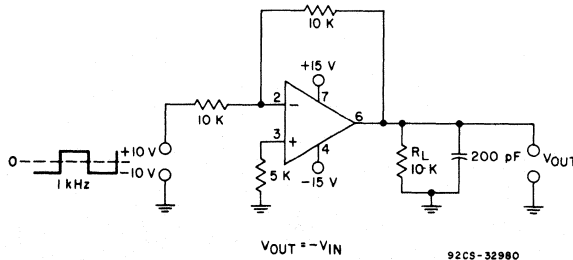
92CS-33672

Test Circuits



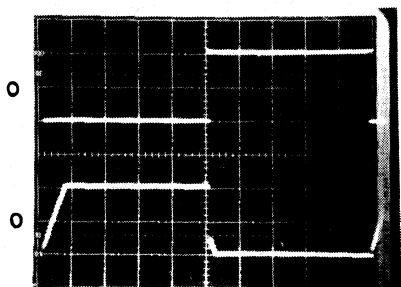
92CS-32979

Fig. 16 - Input offset voltage test circuit.



92CS-32980

a



b

TOP TRACE : INPUT VOLTAGE
BOTTOM TRACE : OUTPUT VOLTAGE

VERT. : $\frac{10V}{DIV}$

V⁺ = 15 V
V⁻ = -15 V

HOR. : $\frac{.1ms}{DIV}$

R_L = 10 K

92CS-32989

Fig. 17 - Inverting amplifier (a) test circuit (b) response to 1-kHz, 20-V p-p square wave.

Linear Integrated Circuits

CA3493, CA3493A, CA3493B

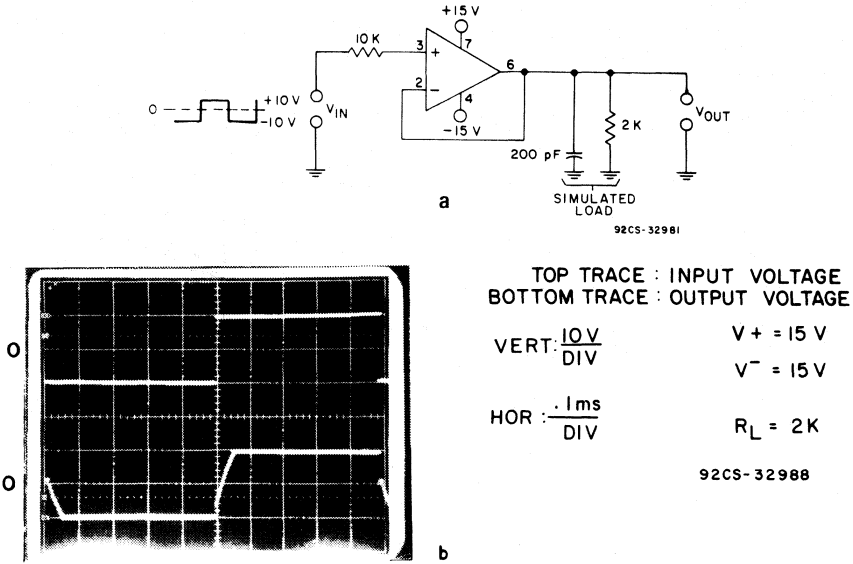


Fig. 18 - Voltage follower (a) test circuit (b) response to 20-V p-p, 1-kHz square-wave input.

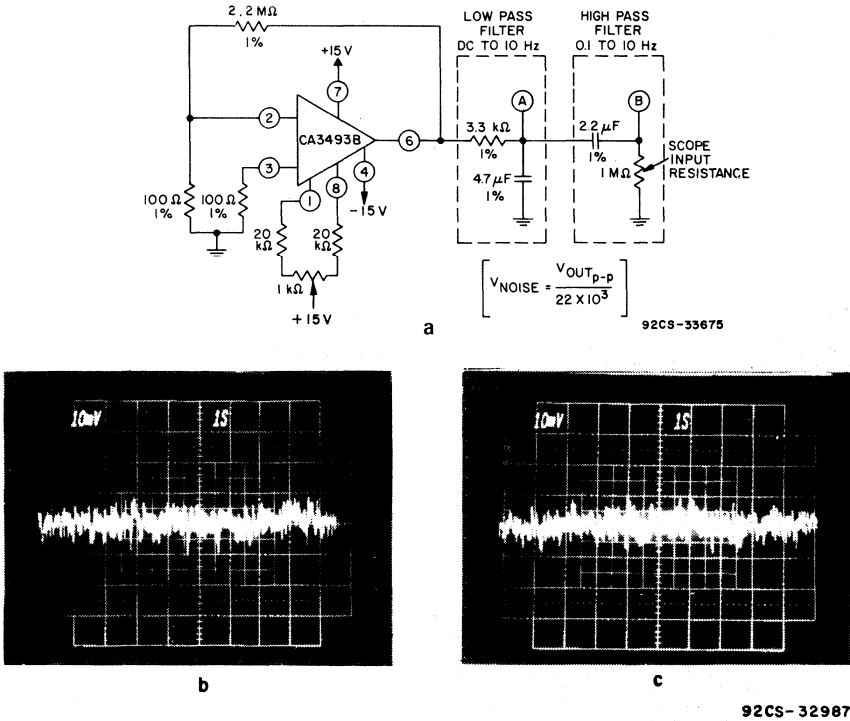
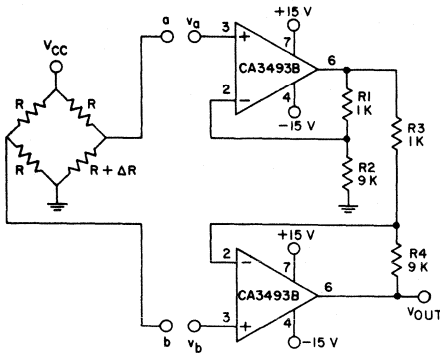


Fig. 19 - Low frequency noise (a) test circuit—0.1 to 10 Hz (b) output A waveform—0 to 10 Hz noise (c) output B waveform—0 to 10 Hz noise.

Application Circuits



$$V_{OUT} = -v_a \left(\frac{R_2}{R_1} + 1 \right) \frac{R_4}{R_3} + v_b \left(\frac{R_4}{R_3} + 1 \right)$$

FOR IDEAL RESISTORS WITH $\frac{R_1}{R_2} = \frac{R_3}{R_4}$

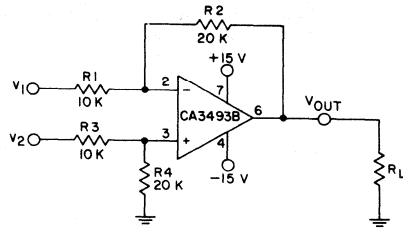
$$V_{OUT} = v_b - v_a \left(\frac{R_4}{R_3} + 1 \right)$$

$$A = \frac{V_{OUT}}{v_b - v_a} = \left(\frac{R_4}{R_3} + 1 \right)$$

FOR VALUES ABOVE $V_{OUT} = (v_b - v_a) (10)$

92CS-33676

Fig. 20 - Typical two-op amp bridge-type differential amplifier.



$$V_{OUT} = v_2 \left(\frac{R_4}{R_3 + R_4} \right) \left(\frac{R_1 + R_2}{R_1} \right) - v_1 \left(\frac{R_2}{R_1} \right)$$

IF $R_4 = R_2, R_3 = R_1$ AND $\frac{R_2}{R_1} = \frac{R_4}{R_3}$

THEN $V_{OUT} = (v_2 - v_1) \left(\frac{R_2}{R_1} \right)$

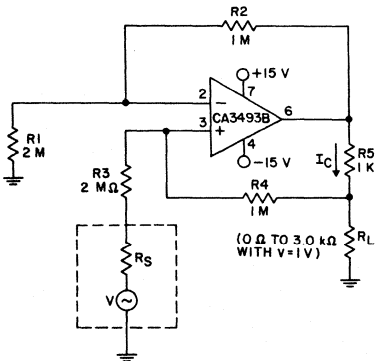
FOR VALUES ABOVE $V_{OUT} = 2(v_2 - v_1)$

IF A_v IS TO BE MADE 1 AND IF $R_1 = R_3 = R_4 = R$ WITH $R_2 = 0.999 R$ (0.1% MISMATCH IN R_2)

THEN $V_{OCM} = 0.0005 V_{IN}$ OR CMRR = 66 dB
 THUS, THE CMRR OF THIS CIRCUIT IS LIMITED BY THE MATCHING OR MISMATCHING OF THIS NETWORK RATHER THAN THE AMPLIFIER.

92CS-33677

Fig. 21 - Differential amplifier (simple subtractor) using CA3493B.



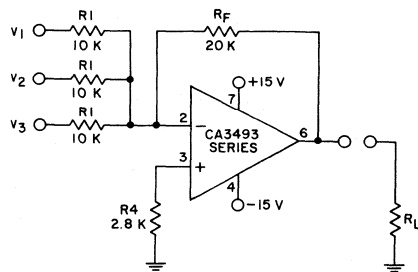
ALL RESISTORS ARE 1%

IF $R_1 = R_3$ AND $R_2 \approx R_4 + R_5$ THEN
 I_L IS INDEPENDENT OF VARIATIONS IN R_L
 FOR R_L VALUES OF 0 Ω TO 3 kΩ WITH $v = 1 V$

$$I_L = \frac{v R_4}{R_3 R_5} = \frac{v (1 M)}{(2 M)(1 K)} = \frac{v}{2 K} = 500 \mu A$$

92CS-33678

Fig. 22 - Using CA3493B as a bilateral current source.



$$V_{OUT} = - \left(\frac{R_F}{R_1} v_1 + \frac{R_F}{R_1} v_2 + \frac{R_F}{R_1} v_3 \right)$$

$$V_{OUT} = - (2 v_1 + 2 v_2 + 2 v_3)$$

92CS-33679

Fig. 23 - Typical summing amplifier application.

Linear Integrated Circuits

CA3493, CA3493A, CA3493B

The CA3493B is an excellent choice for use with thermocouples. In Fig. 24, the CA3493B amplifies the signal generated 500 times. The three 22-megohm resistors

will provide full-scale output if the thermocouple opens.

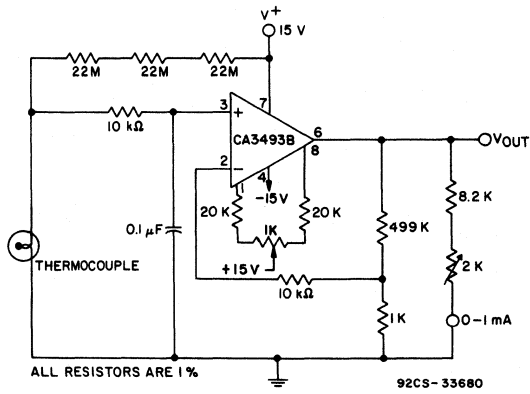
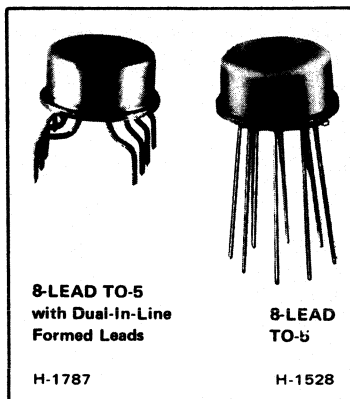


Fig. 24 - The CA3493B used in a thermocouple circuit.



Operational Amplifiers

CA6078AT – Micropower Type

CA6741T – General-Purpose Type

For Applications where Low Noise
(Burst + 1/f) is a Prime Requirement

Virtually free from "popcorn" (burst) noise:
device rejected if any noise burst exceeds 20 μV (peak),
referred to input over a 30-second time period.

RCA-CA6078AT and CA6741T* are low-noise linear IC operational amplifiers that are virtually free of "popcorn" (burst) noise.

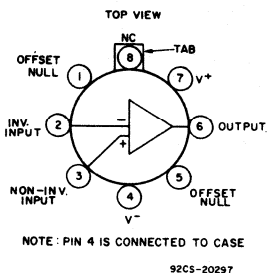
These low-noise versions of the CA3078AT and CA3741T are a result of improved processing developments and rigid burst-noise inspection criteria. A highly selective test circuit (See Fig. 2) assures that each type meets the rigid low-noise standards shown in the data section. This low-burst-noise property also assures excellent performance throughout the 1/f noise spectrum.

In addition the CA6078AT and CA6741T offer the same features incorporated in the CA3078AT and CA3741T respectively, including output short-circuit protection, latch-free operation, wide common-mode and differential-mode signal ranges, and low-offset nulling capability.

For detailed data, characteristics curves, schematic diagram, dimensional outline, and test circuits, refer to the Operational Amplifier Data Bulletins File No. 531 and 535. In addition, for details of considerations in burst-noise measurements, refer to Application Note, ICAN-6732, "Measurement of Burst ("Popcorn") Noise in Linear IC's".

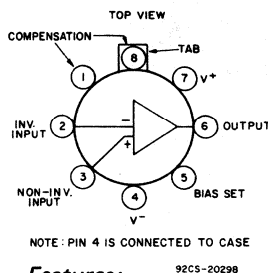
The CA6078AT and CA6741T utilize the hermetically sealed 8-lead TO-5 type package. The CA6078AT and the CA6741T can also be supplied on request with dual-in-line formed leads. These types are identified as the CA6078AS and CA6741S. This formed-lead configuration conforms to that of the 8-lead dual-in-line (Mini-Dip) package. For terminal arrangements, see page 4.

* Formerly Dev. No. TA5807X and TA6029 respectively.



Features:

- Internal phase compensation
- Input bias current: 500 nA max.
- Input offset current: 200 nA max.
- Open-loop voltage gain: 50,000 (94 dB) min.
- Input offset voltage: 5 mV max.



Features:

- Open-loop voltage gain: 40,000 (92 dB) min.
- Input offset voltage: 3.5 mV max.
- Operates with low total supply voltage: 1.5 V min. (± 0.75 V)
- Low quiescent operating current: adjustable for application optimization
- Input bias current: adjustable to below 1 nA

Linear Integrated Circuits

CA6078, CA6741

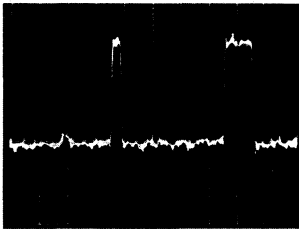
MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

	CA6741T	CA6078AT
DC Supply Voltage (between V^+ and V^- terminals)	44 V	36 V
Differential-Mode Input Voltage	± 30 V	± 6 V
Common-Mode DC Input Voltage [▲]	± 15 V	V^+ to V^-
Device Dissipation:		
Up to 75°C (CA6741T), Up to 125° (CA6078AT)	500 mW	250 mW
Above 75°C	Derate linearly 5 mW/ $^\circ\text{C}$	—
Temperature Range:		
Operating	-55 to $+125^\circ\text{C}$	-55 to $+125^\circ\text{C}$
Storage	-65 to $+150^\circ\text{C}$	-65 to $+150^\circ\text{C}$
Output Short-Circuit Duration [●]	No limitation	No limitation
Lead Temperature (During soldering):		
At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm)		
from case for 10 seconds max.	300 $^\circ\text{C}$	300 $^\circ\text{C}$

[▲]If Supply Voltage is less than ± 15 volts, the Absolute Maximum Input Voltage is equal to the Supply Voltage.

[●]Short circuit may be applied to ground or to either supply.

BURST-NOISE OUTPUT—20 $\mu\text{V}/\text{DIV}$.
REF. TO INPUT

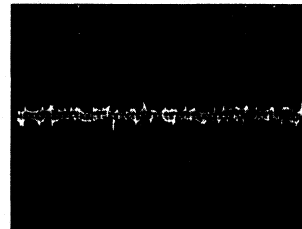


TIME — 10 ms/DIV.

92CS-20299

a. Typ. device with high-burst-noise characteristic.

BURST-NOISE OUTPUT—10 $\mu\text{V}/\text{DIV}$.
REF. TO INPUT

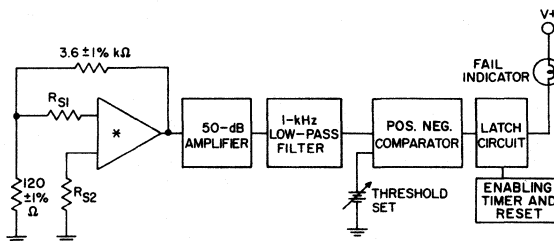


TIME — 20 ms/DIV.

92CS-20300

b. Typ. device controlled for burst noise.

Fig.1—Typ. waveforms of type with high burst noise and type controlled for burst noise.



R_{S1} & $R_{S2} = 100\text{k}\Omega$ FOR CA6741T AND $200\text{k}\Omega$ FOR CA6078AT
* CA6741T OR CA6078AT

92CS-19423

Fig.2—Block diagram of burst-noise "popcorn" test equipment.

Operational Amplifiers

CA6078, CA6741

ELECTRICAL CHARACTERISTICS – CA6078AT, For Equipment Design.

CHARACTERISTICS	SYMBOLS	TEST CONDITIONS Supply Volts: $V^+ = 6, V^- = -6$ $T_A = 25^\circ\text{C}, I_Q = 20 \mu\text{A}$	LIMITS			UNITS
			MIN.	TYP.	MAX.	
Noise Characteristic						
“Popcorn” (Burst) Noise		Bandwidth = 1 kHz $R_{S1} = R_{S2} = 200 \text{ k}\Omega$	Device is rejected if the total noise voltage (burst + $1/f$), referred to input, exceeds 20 μV peak, during a 30-sec. test period.			
Principal Characteristics (For detailed Electrical Characteristics refer to CA3078AT Data Bulletin, File No. 535.)						
Input Offset Voltage	V_{IO}	$R_S \leq 10 \text{ k}\Omega$	–	0.7	3.5	mV
Input Offset Current	I_{IO}		–	0.5	2.5	nA
Input Bias Current	I_{IB}		–	7	12	nA
Open-Loop Differential Voltage Gain	AOL	$R_L \geq 10 \text{ k}\Omega$ $V_O = \pm 4\text{V}$	40,000 92	100,000 100	–	– dB
Common-Mode Input Voltage Range	V_{ICR}	$V^+ = V^- = 15 \text{ V}$	± 14	–	–	V
Common-Mode Rejection Ratio	CMRR	$R_S \leq 10 \text{ k}\Omega$	80	115	–	dB
Output Voltage Swing	$V_{O(P-P)}$	$R_L \geq 10 \Omega$ $R_L \geq 2 \text{ k}\Omega$	± 13.7 –	± 14.1 ± 14	–	– V
Supply Current	I_Q		–	20	25	μA

ELECTRICAL CHARACTERISTICS – CA6741T, For Equipment Design.

CHARACTERISTICS	SYMBOLS	TEST CONDITIONS Supply Volts; $V^+ = 15, V^- = -15$ $T_A = 25^\circ\text{C}$	LIMITS			UNITS
			MIN.	TYP.	MAX.	
Noise Characteristic						
“Popcorn” (Burst) Noise		Bandwidth = 1 kHz $R_{S1} = R_{S2} = 100 \text{ k}\Omega$	Device is rejected if the total noise voltage (burst + $1/f$), referred to input, exceeds 20 μV peak, during a 30-sec. test period.			
Principal Characteristics (For detailed Electrical Characteristics refer to CA3741T Data Bulletin, File No. 531.)						
Input Offset Voltage	V_{IO}	$R_S \leq 10 \text{ k}\Omega$	–	1	5	mV
Input Offset Current	I_{IO}		–	20	200	nA
Input Bias Current	I_{IB}		–	80	500	nA
Open-Loop Differential Voltage Gain	AOL	$R_L \geq 2 \text{ k}\Omega$ $V_O = \pm 10 \text{ V}$	50,000 94	200,000 106	–	– dB
Common-Mode Input Voltage Range	V_{ICR}		± 12	± 13	–	V
Common-Mode Rejection Ratio	CMRR	$R_S \leq 10 \text{ k}\Omega$	70	90	–	dB
Output Voltage Swing	$V_{O(P-P)}$	$R_L \geq 10 \text{ k}\Omega$ $R_L \geq 2 \text{ k}\Omega$	± 12 ± 10	± 14 ± 13	–	– V
Supply Current	I_Q		–	1.7	2.8	mA

Linear Integrated Circuits

CA6078, CA6741

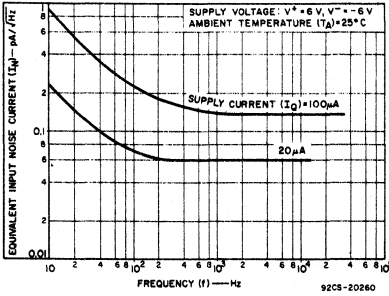


Fig. 3— I_N vs. Frequency for CA6078AT.

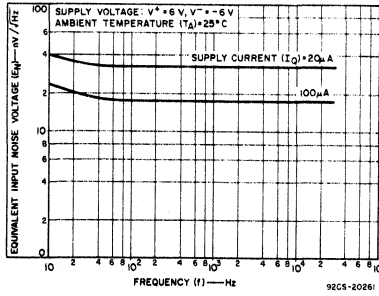


Fig. 4— E_N vs. Frequency for CA6078AT.

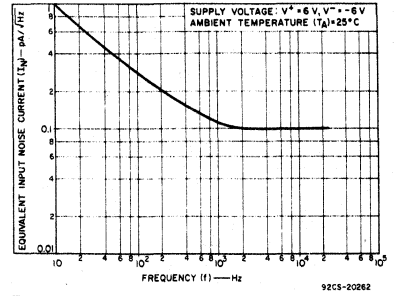


Fig. 5— I_N vs. Frequency for CA6741T.

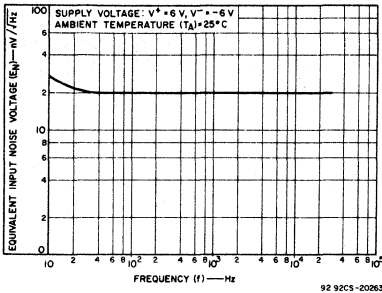


Fig. 6— E_N vs. Frequency for CA6741T.

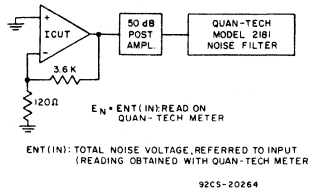


Fig. 7—Test block diagram for E_N .

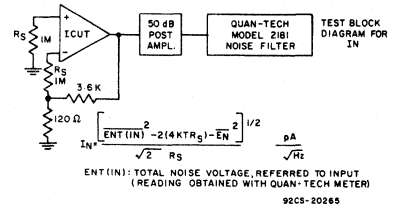
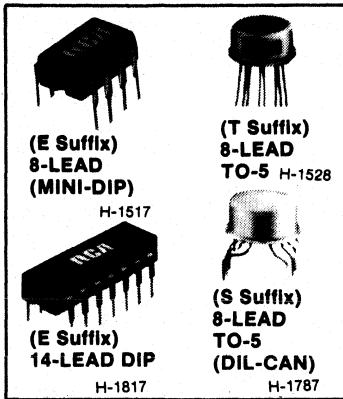


Fig. 8—Test block diagram for I_N .

CA080, CA081, CA082, CA083, CA084 Series

BiMOS Operational Amplifiers

With MOS/FET Input, Composite Bipolar/MOS Output



Single Amplifier: CA080, CA081
Dual Amplifier: CA082, CA083
Quad Amplifier: CA084

Features:

- Very low input bias and offset currents
- Input impedance typically $1.5 \times 10^{12} \Omega$
- Low input offset voltage
- Wide common-mode input voltage range
- Low power consumption
- Fast slew rate
- Unity-gain bandwidth = 5 MHz (typ.)
- Wide output voltage swing

The RCA-CA080, CA081, CA082, CA083, and CA084 BiMOS operational amplifiers combine the advantages of MOS and bipolar transistors on the same monolithic chip. The gate-protected MOS/FET (PMOS) input transistors provide high input impedance and a wide common-mode input voltage range. The bipolar and MOS output transistors allow a wide output voltage swing and provide a high output current capability.

- Low distortion
- Continuous short circuit protection
- Direct replacement for industry type TL080 series in most applications

Applications:

- Inverters
- High-Q notch filters
- IC preamplifiers
- Unity Gain Absolute Value Amplifiers
- Sample and hold amplifiers
- Active filters

Package Selection Chart

Type No.	Package Type & Suffix			
	8L TO-5	DIL-CAN	Mini-DIP	14L DIP
CA080	T	S	E	
CA080A	T	S	E	
CA080B			E	
CA080C	T	S		
CA081	T	S	E	
CA081A	T	S	E	
CA081B			E	
CA081C	T	S		
CA082	T	S	E	
CA082A	T	S	E	
CA082B			E	
CA082C	T	S		
CA083				E
CA083A				E
CA083B				E
CA084				E
CA084A				E
CA084B				E

The CA080 is externally phase-compensated, and the CA081, CA082, CA083, and CA084 are internally phase-compensated. All types except the CA082 have provisions for external offset nulling.

The CA080, CA081, CA082, CA083, and CA084 are available in chip form (H Suffix).

Operating Temperature Ranges:

-55 to +125° C0 to +70° C

CA080T, CA080S

CA080CT, CA080CS

CA080AT, CA080AS

CA080BE

CA081T, CA081S

CA081CT, CA081CS

CA081AT, CA081AS

CA081BE

CA082T, CA082S

CA082CT, CA082CS

CA082AT, CA082AS

CA082BE

CA083BE, CA083AE

CA083BE

CA084, CA084AE

CA084BE

Linear Integrated Circuits

CA080, CA081, CA082, CA083, CA084 Series

MAXIMUM RATINGS, Absolute Maximum Values:

DC SUPPLY VOLTAGE V_{\pm}	± 18 V
DIFFERENTIAL INPUT VOLTAGE	± 16 V
INPUT VOLTAGE RANGE	± 15 V
INPUT CURRENT	1 mA
OUTPUT SHORT-CIRCUIT DURATION	UNLIMITED*
POWER DISSIPATION, P_d :	
At $T_A = 25^{\circ}\text{C}$:	
E Suffix	625 mW
T Suffix	680 mW
Derating Factors:	
Mini-DIP	Derate linearly at 6.67 mW/ $^{\circ}\text{C}$ above 56°C
14-Lead DIP	Derate linearly at 6.67 mW/ $^{\circ}\text{C}$ above 56°C
TO-5	Derate linearly at 6.67 mW/ $^{\circ}\text{C}$ above 56°C
AMBIENT TEMPERATURE RANGE:	
CT, CS, E, Suffixes	0 to $+70^{\circ}\text{C}$
T, S, Suffixes	-55 to $+125^{\circ}\text{C}$
STORAGE TEMPERATURE RANGE, ALL TYPES	-85 to $+150^{\circ}\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance $1/16 \pm 1/32$ (1.59 ± 0.79 mm) from case for 10 seconds max.	$+265^{\circ}\text{C}$

* The output may be shorted to ground or either supply if the maximum temperature and dissipation ratings are observed.

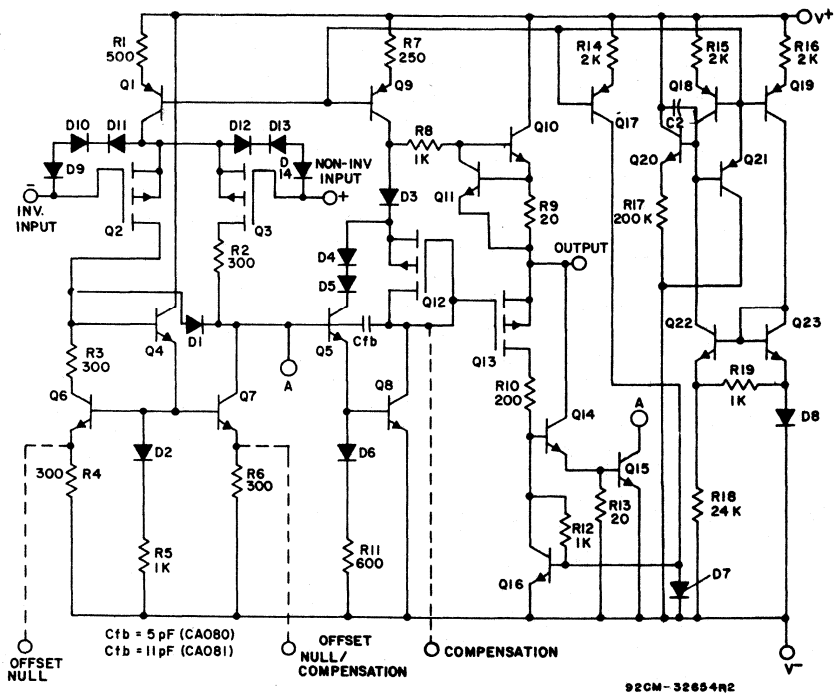


Fig. 1 - Schematic diagram of the CA080, CA081, CA082, CA083, and CA084.

CA080, CA081, CA082, CA083, CA084 Series

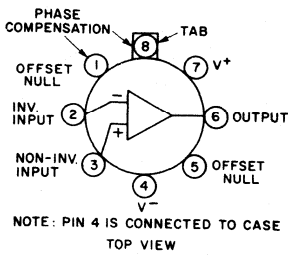
Texas Instruments-to-RCA Package Suffix Cross Reference Chart

Texas Instruments

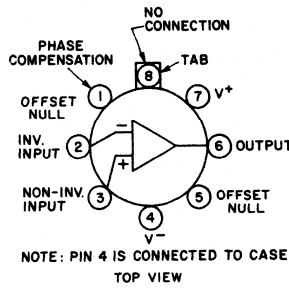
Suffix	Description
ACJG	Ceramic DIL
ACL	TO-5
ACN	Plastic DIL
ACP	Plastic DIL
CJG	Ceramic DIL
CL	TO-5
CN	Plastic DIL
CP	Plastic DIL
IJG	Ceramic DIL
IL	TO-5
IP	Plastic DIL
MJG	Ceramic DIL
ML	TO-5
AML	TO-5
BCP	Plastic DIL

RCA

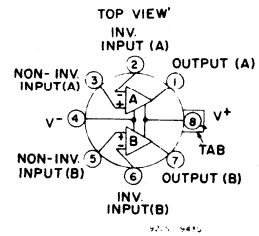
Suffix	Description
AS	DILCAN TO-5
AT	TO-5
AE	Plastic DIL
AE	Plastic DIL
CS	DILCAN TO-5
CT	TO-5
E	Plastic DIL
E	Plastic DIL
S	DILCAN TO-5
T	TO-5
E	DILCAN TO-5
S	DILCAN TO-5
T	TO-5
AT	TO-5
BE	Plastic DIL



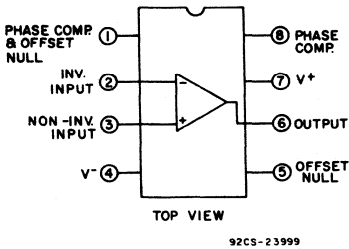
CA080
T, S Suffixes



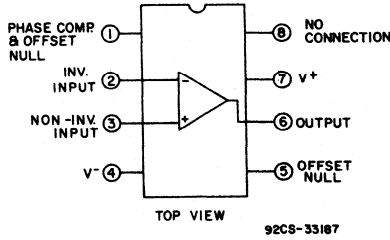
CA081
T, S Suffixes



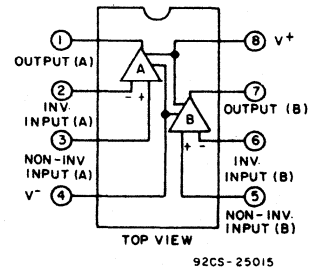
CA082
T, S Suffixes



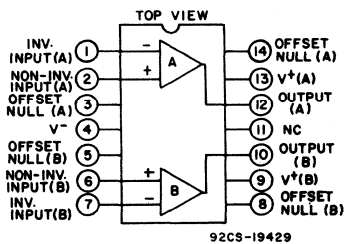
CA080
E Suffix



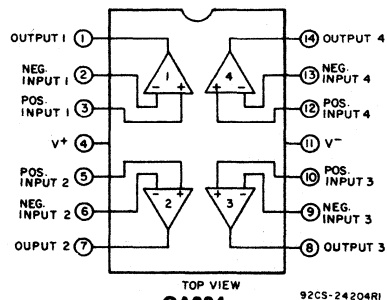
CA081
E Suffix



CA082
E Suffix



CA083
E Suffix



CA084
E Suffix

Fig. 2 - Terminal assignments.

Linear Integrated Circuits

CA080, CA081, CA082, CA083, CA084 Series

TYPICAL OPERATING CHARACTERISTICS at $V_{\pm} = 15\text{ V}$, $T_A = 25^{\circ}\text{C}$

CHARACTERISTIC	TEST CONDITIONS	VALUE	UNITS
Slew Rate at Unity Gain, SR	$V_I = 10\text{ V}$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, $A_{VD} = 1$	13	$\text{V}/\mu\text{s}$
Rise Time, t_r	$V_I = 10\text{ V}$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, $A_{VD} = 1$	0.1	μs
Overshoot Factor	$C_L = 100\text{ pF}$, $A_{VD} = 1$	10	%
Equivalent Input Noise Voltage, e_n	$R_S = 100\ \Omega$, $f = 1\text{ kHz}$	40	$\text{nV}/\sqrt{\text{Hz}}$

ELECTRICAL CHARACTERISTICS at $T_A = 25^{\circ}\text{C}$ and $T_A = -55$ to $+125^{\circ}\text{C}$ for types supplied in TO-5 style packages (T, S Suffixes). $V_{\pm} = \pm 15\text{ V}$

This does not include CA080C, CA081C, or CA082C. These types are supplied in TO-5 packages, but they are specified over the range of 0 to 70°C , and their limits are the same as those for the CA080, CA081, CA082, and CA083 in plastic packages over the range 0 to 70°C .

CHARACTERISTIC	TEST CONDITIONS	LIMITS						UNITS		
		CA080T, S CA081T, S CA082T, S			CA080AT, S CA081AT, S CA082AT, S					
		Min.	Typ.	Max.	Min.	Typ.	Max.			
Input Offset Voltage, V_{IO}	$R_S = 50\ \Omega$	-55 to $+125^{\circ}\text{C}$	X	—	3	6	—	2	3	mV
		$+25^{\circ}\text{C}$	X	—	—	9	—	—	5	
Temperature Coefficient of Input Offset Voltage, αV_{IO}	$R_S = 50\ \Omega$	-55 to $+125^{\circ}\text{C}$	X	—	10	—	—	10	—	$\mu\text{V}/^{\circ}\text{C}$
Input Offset Current, I_{IO}		-55 to $+125^{\circ}\text{C}$	X	—	5	20	—	5	20	pA
		$+25^{\circ}\text{C}$	X	—	—	4	—	—	2	nA
Input Current		-55 to $+125^{\circ}\text{C}$	X	—	15	40	—	15	40	pA
		$+25^{\circ}\text{C}$	X	—	—	10	—	—	5	nA
Common-Mode Input Voltage Range, V_{ICR}		-55 to $+125^{\circ}\text{C}$	X	± 12	—	—	± 12	—	—	V
Maximum Output Voltage Swing, V_{OP-P}	$R_L = 10\text{ k}\Omega$	-55 to $+125^{\circ}\text{C}$	X	24	27	—	24	27	—	V
	$R_L \geq 10\text{ k}\Omega$	$+25^{\circ}\text{C}$	X	24	—	—	24	—	—	
	$R_L \geq 2\text{ k}\Omega$	-55 to $+125^{\circ}\text{C}$	X	20	24	—	20	24	—	
Large-Signal Differential Voltage Gain, A_{VD}	$R_L \geq 2\text{ k}\Omega$, $V_O = \pm 10\text{ V}$	-55 to $+125^{\circ}\text{C}$	X	50	200	—	50	200	—	V/mV
		$+25^{\circ}\text{C}$	X	25	—	—	25	—	—	
Unity-Gain Bandwidth		-55 to $+125^{\circ}\text{C}$	X	—	5	—	—	5	—	MHz
Input Resistance, R_i		-55 to $+125^{\circ}\text{C}$	X	—	1.5	—	—	1.5	—	$\text{T}\Omega$
Common-Mode Rejection Ratio, CMRR	$R_S \leq 10\text{ k}\Omega$	-55 to $+125^{\circ}\text{C}$	X	80	86	—	80	86	—	dB
Power Supply Rejection Ratio, PSRR ($\Delta V_{\pm} / \pm \Delta V_{IO}$)	$R_S \leq 10\text{ k}\Omega$	-55 to $+125^{\circ}\text{C}$	X	80	86	—	80	86	—	dB
Supply Current, I_{\pm} (per amp., CA082, CA083)	No load, No Signal	-55 to $+125^{\circ}\text{C}$	X	—	1.4	2.8	—	1.4	2.8	mA
Channel Separation, V_{O1}/V_{O2} (between amps., CA082, CA083)	$A_{VD} = 100$	-55 to $+125^{\circ}\text{C}$	X	—	120	—	—	120	—	dB

CA080, CA081, CA082, CA083, CA084 Series

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $T_A = 0$ to $+70^\circ\text{C}$
for types supplied in plastic dual-in-line packages (E Suffix). $V^+ = \pm 15\text{ V}$

CHARACTERISTIC	TEST CONDITIONS		LIMITS						UNITS	
			CA080BE CA081BE CA082BE CA083BE CA084BE			CA080AE CA081AE CA082AE CA083AE CA084AE				
			Min.	Typ.	Max.	Min.	Typ.	Max.		
Input Offset Voltage, V_{IO}	$R_S = 50\Omega$	0 to 70°C	X	—	2	3	—	3	6	mV
		$+25^\circ\text{C}$	X	—	—	5	—	—	7.5	
Temperature Coefficient of Input Offset Voltage, αV_{IO}	$R_S = 50\Omega$		X	—	10	—	—	10	—	$\mu\text{V}/^\circ\text{C}$
Input Offset Current, I_{IO}			X	—	5	10	—	5	20	pA
			X	—	—	0.4	—	—	0.6	nA
Input Current			X	—	15	30	—	15	40	pA
			X	—	—	0.7	—	—	1	nA
Common-Mode Input Voltage Range, V_{ICR}			X	± 12	—	—	± 12	—	—	V
Maximum Output Voltage Swing, V_{OP-P}	$R_L = 10\text{ k}\Omega$		X	24	27	—	24	27	—	V
	$R_L \geq 10\text{ k}\Omega$		X	24	—	—	24	—	—	
	$R_L \geq 2\text{ k}\Omega$		X	20	24	—	20	24	—	
Large-Signal Differential Voltage Gain, A_{VD}	$R_L \geq 2\text{ k}\Omega$, $V_O = \pm 10\text{V}$		X	50	200	—	50	200	—	V/mV
			X	—	—	—	—	—	—	
Unity-Gain Bandwidth			X	—	5	—	—	5	—	MHz
Input Resistance, R_i			X	—	1.5	—	—	1.5	—	$\text{T}\Omega$
Common-Mode Rejection Ratio, CMRR	$R_S \leq 10\text{ k}\Omega$		X	80	86	—	80	86	—	dB
Power Supply Rejection Ratio, PSRR ($\Delta V + / \pm \Delta V_{IO}$)	$R_S \leq 10\text{ k}\Omega$		X	80	86	—	80	86	—	dB
Supply Current, I^+ (per amp., CA082, CA083, CA084)	No load, No Signal		X	—	1.4	2.8	—	1.4	2.8	mA
Channel Separation, V_{O1}/V_{O2} (between amps., CA082, CA083)	$A_{VD} = 100$		X	—	120	—	—	120	—	dB

Linear Integrated Circuits

CA080, CA081, CA082, CA083, CA084 Series

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $T_A = 0$ to 70°C for types supplied in plastic dual-in-line packages (E Suffix). $V^+ = \pm 15\text{ V}$

The limits for the CA080C, CA081C, and CA082C in TO-5 packages are the same as those for the types in this chart.

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS		
		CA080E, T CA081E, T CA082E, T CA083E CA084E					
		Min.	Typ.	Max.			
Input Offset Voltage, V_{IO}	$R_S = 50\Omega$	0 to 70°C	X	—	5	15	mV
		+ 25°C	X	—	—	20	
Temperature Coefficient of Input Offset Voltage, αV_{IO}	$R_S = 50\Omega$		X	—	10	—	$\mu\text{V}/^\circ\text{C}$
Input Offset Current, I_{IO}			X	—	5	30	pA
			X	—	—	1	nA
Input Current			X	—	15	50	pA
			X	—	—	2	nA
Common-Mode Input Voltage Range, V_{ICR}			X	± 10	—	—	V
Maximum Output Voltage Swing, V_{OP-P}	$R_L = 10\text{ k}\Omega$		X	24	27	—	V
	$R_L \geq 10\text{ k}\Omega$		X	24	—	—	
	$R_L \geq 2\text{ k}\Omega$		X	20	24	—	
Large-Signal Differential Voltage Gain, A_{VD}	$R_L \geq 2\text{ k}\Omega$, $V_O = \pm 10\text{V}$		X	25	200	—	V/mV
			X	—	—	—	
Unity-Gain Bandwidth			X	—	5	—	MHz
Input Resistance, R_i			X	—	1.5	—	T Ω
Common-Mode Rejection Ratio, CMRR	$R_S \leq 10\text{ k}\Omega$		X	70	76	—	dB
Power Supply Rejection Ratio, PSRR ($\Delta V^+ / \pm \Delta V_{IO}$)	$R_S \leq 10\text{ k}\Omega$		X	70	76	—	dB
Supply Current, I^+ (per amp., CA082, CA083)	No load, No Signal		X	—	1.4	2.8	mA
Channel Separation, V_{O1}/V_{O2} (between amps., CA082, CA083)	$A_{VD} = 100$		X	—	120	—	dB

CA080, CA081, CA082, CA083, CA084 Series

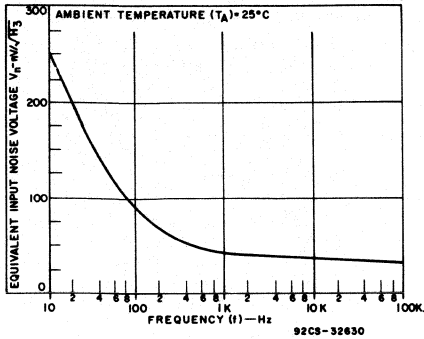


Fig. 3 - Noise voltage as a function of frequency.

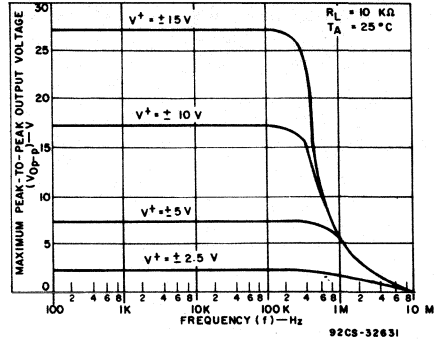


Fig. 4 - Output voltage as a function of frequency.

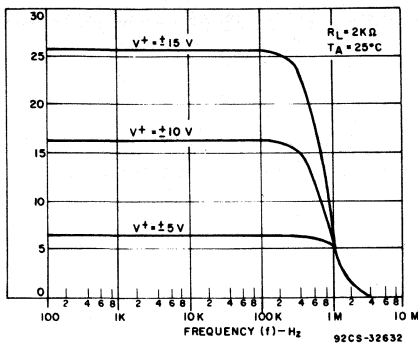


Fig. 5 - Output voltage as a function of frequency.

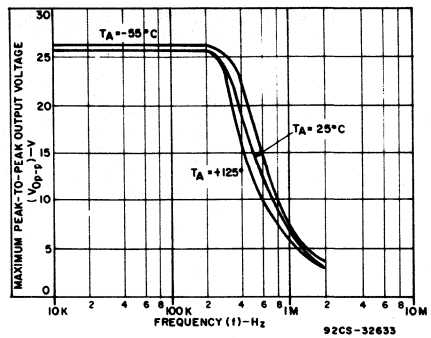


Fig. 6 - Output voltage as a function of frequency.

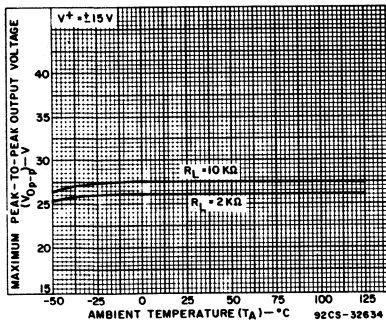


Fig. 7 - Output voltage as a function of ambient temperature.

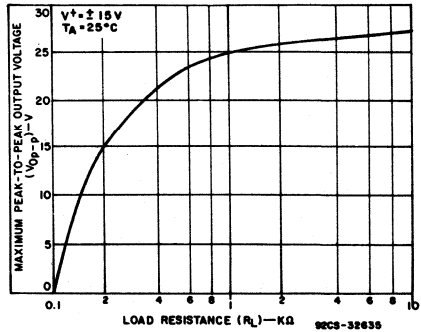


Fig. 8 - Output voltage as a function of load resistance.

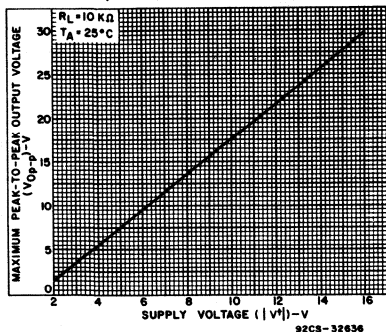


Fig. 9 - Output voltage as a function of supply voltage.

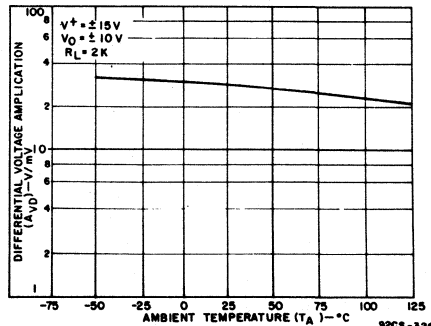


Fig. 10 - Differential voltage amplification as a function of ambient temperature.

Linear Integrated Circuits

CA080, CA081, CA082, CA083, CA084 Series

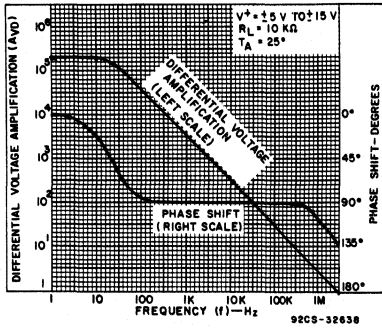


Fig. 11 - Differential voltage amplification as a function of frequency.

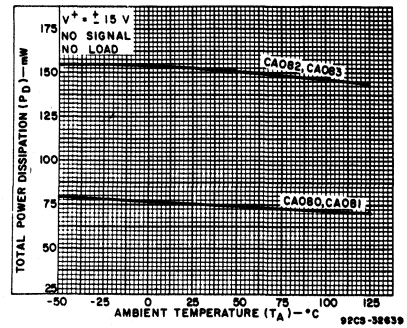


Fig. 12 - Total power dissipation as a function of ambient temperature.

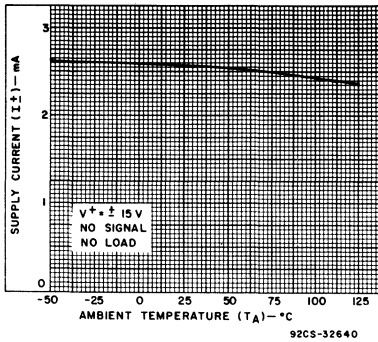


Fig. 13 - Supply current as a function of ambient temperature.

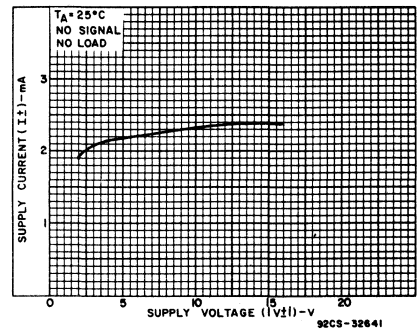


Fig. 14 - Supply current as a function of supply voltage.

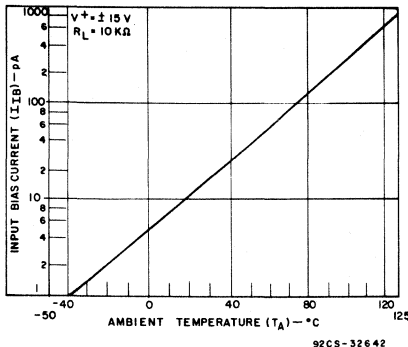


Fig. 15 - Input bias current as a function of ambient temperature.

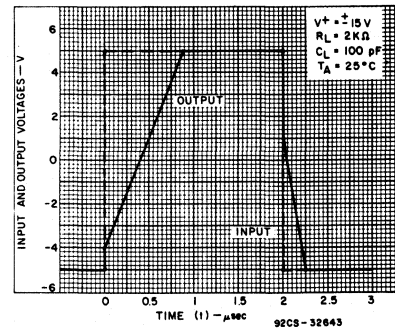


Fig. 16 - Voltage follower large-signal pulse response.

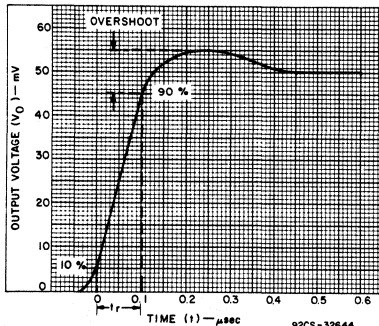


Fig. 17 - Output voltage as a function of elapsed time.

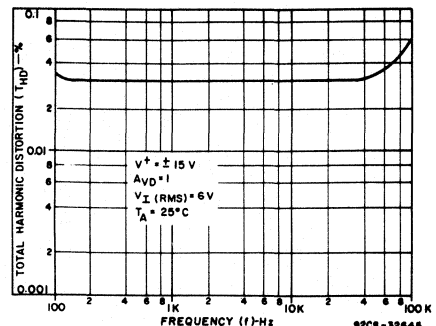


Fig. 18 - Total harmonic distortion as a function of frequency.

CA080, CA081, CA082, CA083, CA084 Series

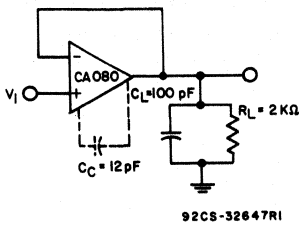


Fig. 19 - Unity-gain amplifier.

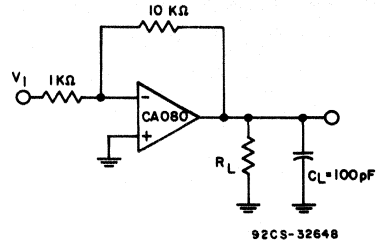


Fig. 20 - 10X inverting amplifier.

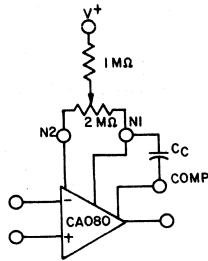


Fig. 21 - Input-offset voltage null circuits.

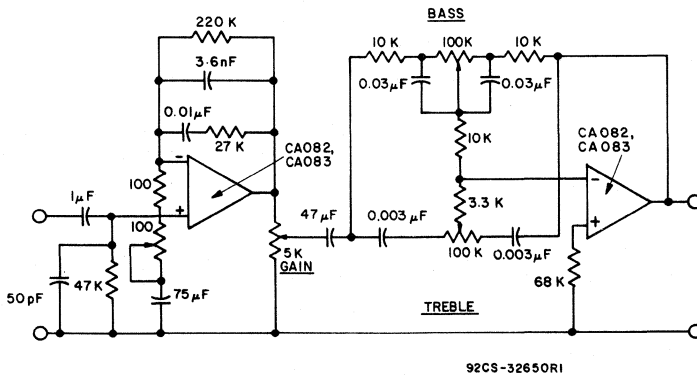
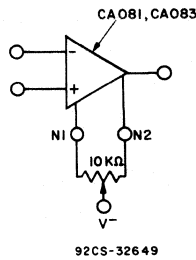


Fig. 22 - IC preamplifier.

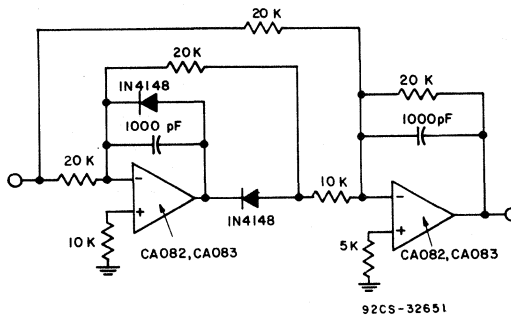


Fig. 23 - Unity-gain absolute-value amplifier.

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CA080, CA081, CA082, CA083, CA084 Series

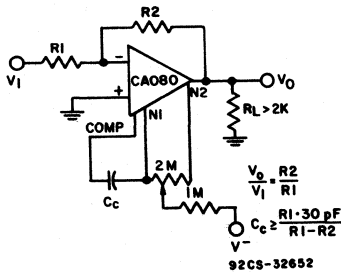


Fig. 24 - Inverting amplifier with single-pole compensation and offset adjustment.

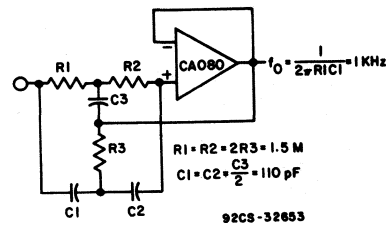


Fig. 25 - High Q notch filter.

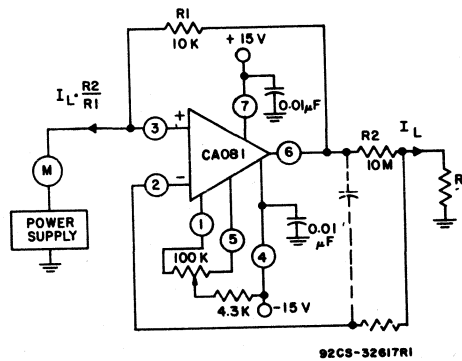


Fig. 26 - Basic current amplifier for low-current measurement systems.

CURRENT AMPLIFIER

The low input-terminal current needed to drive the CA081 makes it ideal for use in current-amplifier applications such as the one shown in Fig.26. In this circuit, low current is supplied at the input potential as the power supply to load resistor R_L . This load current is increased by the multiplication factor R_2/R_1 , when the load current is monitored by the power supply meter M . Thus, if the load current is 100 nA, with values shown, the load current presented to the supply will be 100 μ A; a much easier current to measure in many systems.

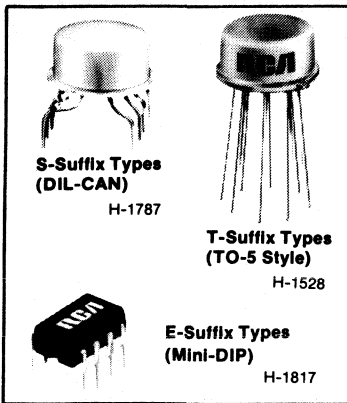
Note that the input and output voltages are transferred at the same potential and only the output current is multiplied by the scale factor.

The dotted components show a method of decoupling the circuit from the effects of high output-load capacitance and the potential oscillation in this situation. Essentially, the necessary high-frequency feedback is provided by the capacitor with the dotted series resistor providing load decoupling.

CA158, CA158A, CA258, CA258A, CA358, CA358A, CA2904 Types

Dual Operational Amplifiers

For Commercial, Industrial, and Military Applications



Features:

- Internal frequency compensation for unity gain
- High dc voltage gain - 100 dB typ.
- Wide bandwidth at unity gain - 1 MHz typ.
- Wide power supply range:
 - Single supply 3 to 30 V
 - Dual supplies ± 1.5 to ± 15 V
- Low supply current - 1.5 mA typ.
- Low input bias current
- Low input offset voltage and current
- Input common-mode voltage range includes ground
- Differential input voltage range equal to V^+ range
- Large output voltage swing - 0 to $V^+ - 1.5$ V

The RCA-CA158, CA158A, CA258, CA258A, CA358, CA358A and CA2904 types consist of two independent, high gain, internally frequency compensated operational amplifiers which are designed specifically to operate from a single power supply over a wide range of voltages. They may also be operated from split power supplies. The supply current is basically independent of the supply voltage over the recommended voltage range.

These devices are particularly useful in interface circuits with digital systems and can be operated from the single common 5 Vdc power supply. They are also intended for transducer amplifiers, dc gain blocks and many other

conventional op amp circuits which can benefit from the single power supply capability.

The CA158, CA158A, CA258, CA258A, CA358, CA358A, and CA2904 types are supplied in 8-lead dual-in-line plastic packages (MINI-DIP, E suffix), 8-lead TO-5 style packages with standard leads (T suffix), and with dual-in-line formed leads (DIL-CAN, S suffix). The CA358 is also supplied in chip form (H suffix).

The CA158, CA158A, CA258, CA258A, CA358, CA358A, and CA2904 types are an equivalent to or a replacement for the industry types 158, 158A, 258, 258A, 358, 358A, and CA2904.

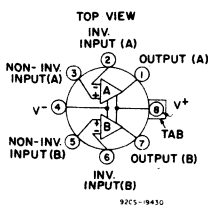


Fig. 1 - Functional diagram for CA158, CA258, and CA358 S- and T-suffix types.

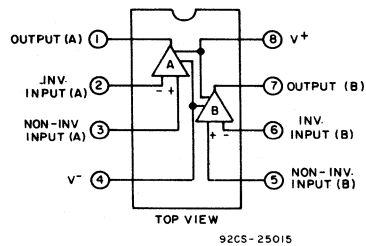


Fig. 2 - Functional diagram for CA158, CA258, CA358, and CA2904 E-suffix types.

Linear Integrated Circuits

CA158, CA158A, CA258, CA258A, CA358, CA358A, CA2904 Types

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

SUPPLY VOLTAGE, V^+ :	
CA2904	26 V or ± 13 V
Other Types	32 V or ± 16 V
DIFFERENTIAL INPUT VOLTAGE:	
All Types	± 32 V
INPUT VOLTAGE	-0.3 V to V^+ V
INPUT CURRENT ($V_I < -0.3$ V) [†]	50 mA
OUTPUT SHORT CIRCUIT TO GROUND	
($V^+ \leq 15$ V)*	Continuous
DEVICE DISSIPATION:	
Up to $T_A = 55^\circ\text{C}$	630 mW
Above $T_A = 55^\circ\text{C}$	derate linearly at 6.67 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:	
Operating	-55 to $+125^\circ\text{C}$
Storage	-65 to $+150^\circ\text{C}$
LEAD TEMPERATURE (During Soldering):	
At distance $1/16 \pm 1/32$ in. (1.59 ± 0.79 mm)	
from case for 10 seconds max.	$+300^\circ\text{C}$

[†] This input current will only exist when the voltage at any of the input leads is driven negative. This current is due to the collector-base junction of the input p-n-p transistors becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also lateral n-p-n parasitic transistor action on the IC chip. This transistor action can cause the output voltages of the amplifiers to go to the V^+ voltage level (or to ground for a large overdrive) for the time duration that an input is driven negative. This transistor action is not destructive and normal output states will re-establish when the input voltage, which was negative, again returns to a value greater than -0.3 V dc.

* The maximum output current is approximately 40 mA independent of the magnitude of V^+ . Continuous short circuits at $V^+ > 15$ V can cause excessive power dissipation and eventual destruction. Short circuits from the output to V^+ can cause overheating and eventual destruction of the device. Destructive dissipation can result from simultaneous short circuits on both amplifiers.

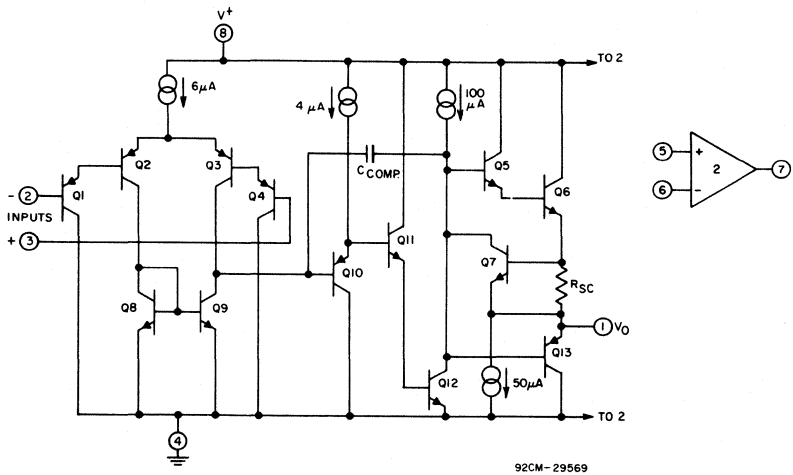


Fig.3 - Schematic diagram - one of two operational amplifiers.

CA158, CA158A, CA258, CA258A, CA358, CA358A, CA2904 Types
ELECTRICAL CHARACTERISTICS (Values Apply For Each Operational Amplifier)

CHARACTERISTIC	TEST CONDITIONS	LIMITS CA158A (E, T, S)			UNITS
		Supply Voltage (V^+) = 5 V Unless Otherwise Specified	Min.	Typ.	
$T_A = 25^\circ\text{C}$					
Input Offset Voltage, V_{IO}	Note 3	–	1	2	mV
Output Voltage Swing, V_{OPP}	$R_L = 2\text{ k}\Omega$	0	–	$V^+ - 1.5$	V
Input Common-Mode Voltage Range, V_{ICR}	Note 2, $V^+ = 30\text{ V}$	0	–	$V^+ - 1.5$	V
Input Offset Current, I_{IO}	$I_1^+ - I_1^-$	–	2	10	nA
Input Bias Current, I_{IB}	I_1^+ or I_1^- , Note 1	–	20	50	nA
Output Current (Source), I_O	$V_1^+ = +1\text{ V}$, $V_1^- = 0\text{ V}$, $V^+ = 15\text{ V}$	20	40	–	mA
Output Current (Sink), I_O	$V_1^+ = 0\text{ V}$, $V_1^- = 1\text{ V}$, $V^+ = 15\text{ V}$	10	20	–	mA
	$V_1^+ = 0\text{ V}$, $V_1^- = 1\text{ V}$, $V_O = 200\text{ mV}$	12	50	–	μA
Short Circuit Output Current	$R_L = 0$ (to Ground) Note 4	–	40	60	mA
Large Signal Voltage Gain, A_{OL}	$R_L \geq 2\text{ k}\Omega$, $V^+ = 15\text{ V}$ (For large V_O swing)	50	100	–	V/mV
Common-Mode Rejection Ratio, CMRR	DC	70	85	–	dB
Power Supply Rejection Ratio, PSRR	DC	65	100	–	dB
Amplifier-to-Amplifier Coupling	$f = 1$ to 20 kHz (Input referred)	–	–120	–	dB
$T_A = -55$ to $+125^\circ\text{C}$					
Input Offset Voltage, V_{IO}	Note 3	–	–	4	mV
Temperature Coefficient of Input Offset Voltage, αV_{IO}	$R_S = 0$	–	7	15	$\mu\text{V}/^\circ\text{C}$
Input Offset Current, I_{IO}	$I_1^+ - I_1^-$	–	–	30	nA
Temperature Coefficient of Input Offset Current, αI_{IO}		–	10	200	$\text{pA}/^\circ\text{C}$
Input Bias Current, I_{IB}	I_1^+ or I_1^-	–	40	100	nA
Input Common-Mode Voltage Range, V_{ICR}	$V^+ = 30\text{ V}$, Note 2	0	–	$V^+ - 2$	V
Supply Current, I^+	$R_L = \infty$ On All Ampl.	–	0.7	1.2	mA
	$R_L = \infty$, $V^+ = 30\text{ V}$	–	1.5	3	

NOTE 1: Due to the p-n-p input stage the direction of the input current is out of the IC. No loading change exists on the input lines because this current is essentially constant, independent of the state of the output.

NOTE 2: The input signal voltages and the input common-mode voltage should not be allowed to go negative by more than 0.3 V. The positive limit of the common-mode voltage range is $V^+ - 1.5\text{ V}$, but either or both inputs can go the + 32 V without damage.

NOTE 3: $V_O = 1.4\text{ V}_{DC}$, $R_S = 0\ \Omega$ with V^+ from 5 V to 30 V, and over the full input common-mode voltage range (0 V to $V^+ - 1.5\text{ V}$).

NOTE 4: The maximum output current is approximately 40 mA independent of the magnitude of V^+ . Continuous short circuits at $V^+ > 15\text{ V}$ can cause excessive power dissipation and eventual destruction. Short circuits from the output to V^+ can cause overheating and eventual destruction of the device. Destructive dissipation can result from simultaneous short circuits on both amplifiers.

Linear Integrated Circuits

CA158, CA158A, CA258, CA258A, CA358, CA358A, CA2904 Types

ELECTRICAL CHARACTERISTICS (Values Apply for Each Operational Amplifier)

CHARACTERISTIC	TEST CONDITIONS	LIMITS CA258A (E, T, S)			UNITS
		Supply Voltage (V^+) = 5 V Unless Otherwise Specified	Min.	Typ.	
$T_A = 25^\circ\text{C}$					
Input Offset Voltage, V_{IO}	Note 3	–	1	3	mV
Output Voltage Swing, V_{OPP}	$R_L = 2\text{ k}\Omega$	0	–	$V^+ - 1.5$	V
Input Common-Mode Voltage Range, V_{ICR}	Note 2, $V^+ = 30\text{ V}$	0	–	$V^+ - 1.5$	V
Input Offset Current, I_{IO}	$I_1^+ - I_1^-$	–	2	15	nA
Input Bias Current, I_{IB}	I_1^+ or I_1^- , Note 1	–	40	80	nA
Output Current (Source), I_O	$V_1^+ = +1\text{ V}$, $V_1^- = 0\text{ V}$, $V^+ = 15\text{ V}$	20	40	–	mA
Output Current (Sink), I_O	$V_1^+ = 0\text{ V}$, $V_1^- = 1\text{ V}$, $V^+ = 15\text{ V}$	10	20	–	mA
	$V_1^+ = 0\text{ V}$, $V_1^- = 1\text{ V}$, $V_O = 200\text{ mV}$	12	50	–	μA
Short Circuit Output Current	$R_L = 0$ (to Ground) Note 4	–	40	60	mA
Large Signal Voltage Gain, A_{OL}	$R_L \geq 2\text{ k}\Omega$, $V^+ = 15\text{ V}$ (For large V_O swing)	50	100	–	V/mV
Common-Mode Rejection Ratio, CMRR	DC	70	85	–	dB
Power Supply Rejection Ratio, PSRR	DC	65	100	–	dB
Amplifier-to-Amplifier Coupling	$f = 1$ to 20 kHz (Input referred)	–	–120	–	dB
$T_A = -25$ to $+85^\circ\text{C}$					
Input Offset Voltage, V_{IO}	Note 3	–	–	4	mV
Temperature Coefficient of Input Offset Voltage, αV_{IO}	$R_S = 0$	–	7	15	$\mu\text{V}/^\circ\text{C}$
Input Offset Current, I_{IO}	$I_1^+ - I_1^-$	–	–	30	nA
Temperature Coefficient of Input Offset Current, αI_{IO}		–	10	200	$\text{pA}/^\circ\text{C}$
Input Bias Current, I_{IB}	I_1^+ or I_1^-	–	40	100	nA
Input Common-Mode Voltage Range, V_{ICR}	$V^+ = 30\text{ V}$, Note 2	0	–	$V^+ - 2$	V
Supply Current, I^+	$R_L = \infty$ On All Ampl.	–	0.7	1.2	mA
	$R_L = \infty$, $V^+ = 30\text{ V}$	–	1.5	3	

NOTE 1: Due to the p-n-p input stage the direction of the input current is out of the IC. No loading change exists on the input lines because this current is essentially constant, independent of the state of the output.

NOTE 2: The input signal voltages and the input common-mode voltage should not be allowed to go negative by more than 0.3 V. The positive limit of the common-mode voltage range is $V^+ - 1.5\text{ V}$, but either or both inputs can go the +32 V without damage.

NOTE 3: $V_O = 1.4\text{ VDC}$, $R_S = 0\ \Omega$ with V^+ from 5 V to 30 V, and over the full input common-mode voltage range (0 V to $V^+ - 1.5\text{ V}$).

NOTE 4: The maximum output current is approximately 40 mA independent of the magnitude of V^+ . Continuous short circuits at $V^+ > 15\text{ V}$ can cause excessive power dissipation and eventual destruction. Short circuits from the output to V^+ can cause overheating and eventual destruction of the device. Destructive dissipation can result from simultaneous short circuits on both amplifiers.

CA158, CA158A, CA258, CA258A, CA358, CA358A, CA2904 Types

ELECTRICAL CHARACTERISTICS (Values Apply for Each Operational Amplifier)

CHARACTERISTIC	TEST CONDITIONS	LIMITS CA358A (E. T. S)			UNITS
		Min.	Typ.	Max.	
$T_A = 25^\circ\text{C}$					
Input Offset Voltage, V_{IO}	Note 3	–	2	3	mV
Output Voltage Swing, V_{OPP}	$R_L = 2\text{ k}\Omega$	0	–	$V^+ - 1.5$	V
Input Common-Mode Voltage Range, V_{ICR}	Note 2, $V^+ = 30\text{ V}$	0	–	$V^+ - 1.5$	V
Input Offset Current, I_{IO}	$I_1^+ - I_1^-$	–	5	30	nA
Input Bias Current, I_{IB}	I_1^+ or I_1^- , Note 1	–	45	100	nA
Output Current (Source), I_O	$V_1^+ = +1\text{ V}$, $V_1^- = 0\text{ V}$, $V^+ = 15\text{ V}$	20	40	–	mA
Output Current (Sink), I_O	$V_1^+ = 0\text{ V}$, $V_1^- = 1\text{ V}$, $V^+ = 15\text{ V}$	10	20	–	mA
	$V_1^+ = 0\text{ V}$, $V_1^- = 1\text{ V}$, $V_O = 200\text{ mV}$	12	50	–	μA
Short Circuit Output Current	$R_L = 0$ (to Ground) Note 4	–	40	60	mA
Large Signal Voltage Gain, A_{OL}	$R_L \geq 2\text{ k}\Omega$, $V^+ = 15\text{ V}$ (For large V_O swing)	25	100	–	V/mV
Common-Mode Rejection Ratio, CMRR	DC	65	85	–	dB
Power Supply Rejection Ratio, PSRR	DC	65	100	–	dB
Amplifier-to-Amplifier Coupling	$f = 1$ to 20 kHz (Input referred)	–	–120	–	dB
$T_A = 0$ to $+70^\circ\text{C}$					
Input Offset Voltage, V_{IO}	Note 3	–	–	5	mV
Temperature Coefficient of Input Offset Voltage, αV_{IO}	$R_S = 0$	–	7	20	$\mu\text{V}/^\circ\text{C}$
Input Offset Current, I_{IO}	$I_1^+ - I_1^-$	–	–	75	nA
Temperature Coefficient of Input Offset Current, αI_{IO}		–	10	300	$\text{pA}/^\circ\text{C}$
Input Bias Current, I_{IB}	I_1^+ or I_1^-	–	40	200	nA
Input Common-Mode Voltage Range, V_{ICR}	$V^+ = 30\text{ V}$, Note 2	0	–	$V^+ - 2$	V
Supply Current, I^+	$R_L = \infty$ On All Ampl.	–	0.7	1.2	mA
	$R_L = \infty$, $V^+ = 30\text{ V}$	–	1.5	3	

NOTE 1: Due to the p-n-p input stage the direction of the input current is out of the IC. No loading change exists on the input lines because this current is essentially constant, independent of the state of the output.

NOTE 2: The input signal voltages and the input common-mode voltage should not be allowed to go negative by more than 0.3 V. The positive limit of the common-mode voltage range is $V^+ - 1.5\text{ V}$, but either or both inputs can go the $+32\text{ V}$ without damage.

NOTE 3: $V_O = 1.4\text{ V}_{DC}$, $R_S = 0\ \Omega$ with V^+ from 5 V to 30 V, and over the full input common-mode voltage range (0 V to $V^+ - 1.5\text{ V}$).

NOTE 4: The maximum output current is approximately 40 mA independent of the magnitude of V^+ . Continuous short circuits at $V^+ > 15\text{ V}$ can cause excessive power dissipation and eventual destruction. Short circuits from the output to V^+ can cause overheating and eventual destruction of the device. Destructive dissipation can result from simultaneous short circuits on both amplifiers.

Linear Integrated Circuits

CA158, CA158A, CA258, CA258A, CA358, CA358A, CA2904 Types

ELECTRICAL CHARACTERISTICS (Values Apply for Each Operational Amplifier)

CHARACTERISTIC	TEST CONDITIONS	LIMITS CA158 (E, T, S) CA258 (E, T, S)			UNITS
		Supply Voltage (V ⁺) = 5 V Unless Otherwise Specified	Min.	Typ.	
T_A = 25°C					
Input Offset Voltage, V _{IO}	Note 3	–	2	5	mV
Output Voltage Swing, V _{OPP}	R _L = 2 kΩ	0	–	V ⁺ – 1.5	V
Input Common-Mode Voltage Range, V _{ICR}	Note 2, V ⁺ = 30 V	0	–	V ⁺ – 1.5	V
Input Offset Current, I _{IO}	I ₁ ⁺ – I ₁ [–]	–	3	30	nA
Input Bias Current, I _{IB}	I ₁ ⁺ or I ₁ [–] , Note 1	–	45	150	nA
Output Current (Source), I _O	V ₁ ⁺ = +1 V, V ₁ [–] = 0 V, V ⁺ = 15 V	20	40	–	mA
Output Current (Sink), I _O	V ₁ ⁺ = 0 V, V ₁ [–] = 1 V, V ⁺ = 15 V	10	20	–	mA
	V ₁ ⁺ = 0 V, V ₁ [–] = 1 V, V _O = 200 mV	12	50	–	μA
Short Circuit Output Current	R _L = 0 (to Ground) Note 4	–	40	60	mA
Large Signal Voltage Gain, A _{OL}	R _L ≥ 2 kΩ, V ⁺ = 15 V (For large V _O swing)	50	100	–	V/mV
Common-Mode Rejection Ratio, CMRR	DC	70	85	–	dB
Power Supply Rejection Ratio, PSRR	DC	65	100	–	dB
Amplifier-to-Amplifier Coupling	f = 1 to 20 kHz (Input referred)	–	–120	–	dB
T_A = –55 to +125°C (CA158); T_A = –25 to +85°C (CA258)					
Input Offset Voltage, V _{IO}	Note 3	–	–	7	mV
Temperature Coefficient of Input Offset Voltage, αV _{IO}	R _s = 0	–	7	–	μV/°C
Input Offset Current, I _{IO}	I ₁ ⁺ – I ₁ [–]	–	–	100	nA
Temperature Coefficient of Input Offset Current, αI _{IO}		–	10	–	pA/°C
Input Bias Current, I _{IB}	I ₁ ⁺ or I ₁ [–]	–	40	300	nA
Input Common-Mode Voltage Range, V _{ICR}	V ⁺ = 30 V, Note 2	0	–	V ⁺ – 2	V
Supply Current, I ⁺	R _L = ∞ On All Ampl.	–	0.7	1.2	mA
	R _L = ∞, V ⁺ = 30 V	–	1.5	3	

NOTE 1: Due to the p-n-p input stage the direction of the input current is out of the IC. No loading change exists on the input lines because this current is essentially constant, independent of the state of the output.

NOTE 2: The input signal voltages and the input common-mode voltage should not be allowed to go negative by more than 0.3 V. The positive limit of the common-mode voltage range is V⁺ – 1.5 V, but either or both inputs can go the +32 V without damage.

NOTE 3: V_O = 1.4 V_{DC}, R_s = 0 Ω with V⁺ from 5 V to 30 V, and over the full input common-mode voltage range (0 V to V⁺ – 1.5 V).

NOTE 4: The maximum output current is approximately 40 mA independent of the magnitude of V⁺. Continuous short circuits at V⁺ > 15 V can cause excessive power dissipation and eventual destruction. Short circuits from the output to V⁺ can cause overheating and eventual destruction of the device. Destructive dissipation can result from simultaneous short circuits on both amplifiers.

CA158, CA158A, CA258, CA258A, CA358, CA358A, CA2904 Types

ELECTRICAL CHARACTERISTICS (Values Apply for Each Operational Amplifier)

CHARACTERISTIC	TEST CONDITIONS	LIMITS CA358 (E, T, S)			UNITS
		Supply Voltage (V^+) = 5 V Unless Otherwise Specified	Min.	Typ.	
$T_A = 25^\circ\text{C}$					
Input Offset Voltage, V_{IO}	Note 3	–	2	7	mV
Output Voltage Swing, V_{OPP}	$R_L = 2\text{ k}\Omega$	0	–	$V^+ - 1.5$	V
Input Common-Mode Voltage Range, V_{ICR}	Note 2, $V^+ = 30\text{ V}$	0	–	$V^+ - 1.5$	V
Input Offset Current, I_{IO}	$I_1^+ - I_1^-$	–	5	50	nA
Input Bias Current, I_{IB}	I_1^+ or I_1^- , Note 1	–	45	250	nA
Output Current (Source), I_O	$V_1^+ = +1\text{ V}$, $V_1^- = 0\text{ V}$, $V^+ = 15\text{ V}$	20	40	–	mA
Output Current (Sink), I_O	$V_1^+ = 0\text{ V}$, $V_1^- = 1\text{ V}$, $V^+ = 15\text{ V}$	10	20	–	mA
	$V_1^+ = 0\text{ V}$, $V_1^- = 1\text{ V}$, $V_O = 200\text{ mV}$	12	50	–	μA
Short Circuit Output Current	$R_L = 0$ (to Ground) Note 4	–	40	60	mA
Large Signal Voltage Gain, A_{OL}	$R_L \geq 2\text{ k}\Omega$, $V^+ = 15\text{ V}$ (For large V_O swing)	25	100	–	V/mV
Common-Mode Rejection Ratio, CMRR	DC	65	70	–	dB
Power Supply Rejection Ratio, PSRR	DC	65	100	–	dB
Amplifier-to-Amplifier Coupling	$f = 1$ to 20 kHz (Input referred)	–	–120	–	dB
$T_A = 0$ to $+70^\circ\text{C}$					
Input Offset Voltage, V_{IO}	Note 3	–	–	9	mV
Temperature Coefficient of Input Offset Voltage, αV_{IO}	$R_S = 0$	–	7	–	$\mu\text{V}/^\circ\text{C}$
Input Offset Current, I_{IO}	$I_1^+ - I_1^-$	–	–	150	nA
Temperature Coefficient of Input Offset Current, αI_{IO}		–	10	–	$\text{pA}/^\circ\text{C}$
Input Bias Current, I_{IB}	I_1^+ or I_1^-	–	40	500	nA
Input Common-Mode Voltage Range, V_{ICR}	$V^+ = 30\text{ V}$, Note 2	0	–	$V^+ - 2$	V
Supply Current, I^+	$R_L = \infty$ On All Ampl.	–	0.7	1.2	mA
	$R_L = \infty$, $V^+ = 30\text{ V}$	–	1.5	3	

NOTE 1: Due to the p-n-p input stage the direction of the input current is out of the IC. No loading change exists on the input lines because this current is essentially constant, independent of the state of the output.

NOTE 2: The input signal voltages and the input common-mode voltage should not be allowed to go negative by more than 0.3 V. The positive limit of the common-mode voltage range is $V^+ - 1.5\text{ V}$, but either or both inputs can go the $+32\text{ V}$ without damage.

NOTE 3: $V_O = 1.4\text{ V}_{DC}$, $R_S = 0\ \Omega$ with V^+ from 5 V to 30 V, and over the full input common-mode voltage range (0 V to $V^+ - 1.5\text{ V}$).

NOTE 4: The maximum output current is approximately 40 mA independent of the magnitude of V^+ . Continuous short circuits at $V^+ > 15\text{ V}$ can cause excessive power dissipation and eventual destruction. Short circuits from the output to V^+ can cause overheating and eventual destruction of the device. Destructive dissipation can result from simultaneous short circuits on both amplifiers.

Linear Integrated Circuits

CA158, CA158A, CA258, CA258A, CA358, CA358A, CA2904 Types

ELECTRICAL CHARACTERISTICS (Values Apply for Each Operational Amplifier)

CHARACTERISTIC	TEST CONDITIONS Supply Voltage (V ⁺) = 5 V Unless Otherwise Specified	LIMITS CA2904E			UNITS
		Min.	Typ.	Max.	
T_A = 25°C					
Input Offset Voltage, V _{IO}	Note 3	–	2	7	mV
Output Voltage Swing, V _{OPP}	R _L = 10 kΩ	0	–	V ⁺ – 1.5	V
Input Common-Mode Voltage Range, V _{ICR}	Note 2, V ⁺ = 30 V	0	–	V ⁺ – 1.5	V
Input Offset Current, I _{IO}	I ₁ ⁺ – I ₁ [–]	–	5	50	nA
Input Bias Current, I _{IB}	I ₁ ⁺ or I ₁ [–] , Note 1	–	45	250	nA
Output Current (Source), I _O	V ₁ ⁺ = +1 V, V ₁ [–] = 0 V, V ⁺ = 15 V	20	40	–	mA
Output Current (Sink), I _O	V ₁ ⁺ = 0 V, V ₁ [–] = 1 V, V ⁺ = 15 V	10	20	–	mA
Short Circuit Output Current	R _L = 0 (to Ground) Note 4	–	40	60	mA
Large Signal Voltage Gain, A _{OL}	R _L ≥ 2 kΩ, V ⁺ = 15 V (For large V _O swing)	–	100	–	V/mV
Common-Mode Rejection Ratio, CMRR	DC	50	70	–	dB
Power Supply Rejection Ratio, PSRR	DC	50	100	–	dB
Amplifier-to-Amplifier Coupling	f = 1 to 20 kHz (Input referred)	–	–120	–	dB
T_A = –40 to +85°C					
Input Offset Voltage, V _{IO}	Note 3	–	–	10	mV
Temperature Coefficient of Input Offset Voltage, αV _{IO}	R _s = 0	–	7	–	μV/°C
Input Offset Current, I _{IO}	I ₁ ⁺ – I ₁ [–]	–	45	200	nA
Temperature Coefficient of Input Offset Current, αI _{IO}		–	10	–	pA/°C
Input Bias Current, I _{IB}	I ₁ ⁺ or I ₁ [–]	–	40	500	nA
Input Common-Mode Voltage Range, V _{ICR}	V ⁺ = 30 V, Note 2	0	–	V ⁺ – 2	V
Supply Current, I ⁺	R _L = ∞ On All Ampl.	–	0.7	1.2	mA
	R _L = ∞, V ⁺ = 30 V	–	1.5	3	

NOTE 1: Due to the p-n-p input stage the direction of the input current is out of the IC. No loading change exists on the input lines because this current is essentially constant, independent of the state of the output.

NOTE 2: The input signal voltages and the input common-mode voltage should not be allowed to go negative by more than 0.3 V. The positive limit of the common-mode voltage range is V⁺ – 1.5 V, but either or both inputs can go the + 32 V without damage.

NOTE 3: V_O = 1.4 V_{DC}, R_s = 0 Ω with V⁺ from 5 V to 30 V, and over the full input common-mode voltage range (0 V to V⁺ – 1.5 V).

NOTE 4: The maximum output current is approximately 40 mA independent of the magnitude of V⁺. Continuous short circuits at V⁺ > 15 V can cause excessive power dissipation and eventual destruction. Short circuits from the output to V⁺ can cause overheating and eventual destruction of the device. Destructive dissipation can result from simultaneous short circuits on both amplifiers.

CA158, CA158A, CA258, CA258A, CA358, CA358A, CA2904 Types

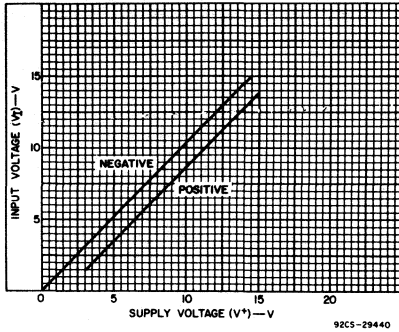


Fig.4 - Input voltage range as a function of supply voltage.

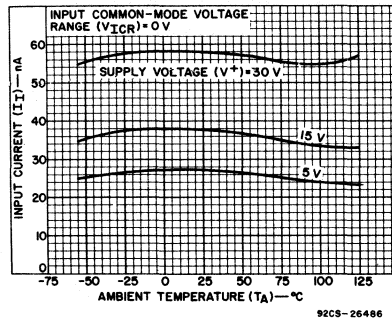


Fig.5 - Input current as a function of ambient temperature.

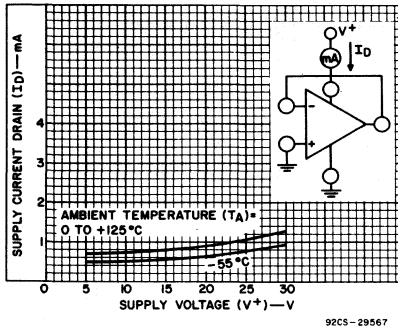


Fig.6 - Supply current drain as a function of supply voltage.

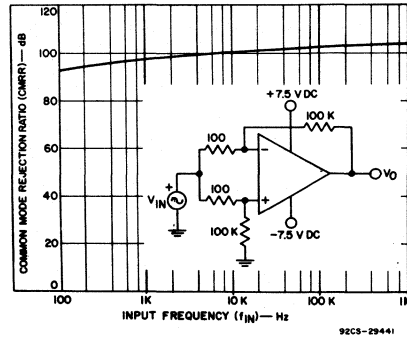


Fig.7 - Common mode rejection ratio as a function of input frequency.

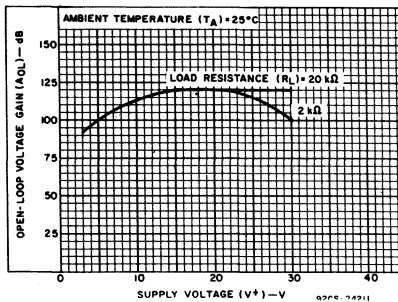


Fig.8 - Voltage gain as a function of supply voltage.

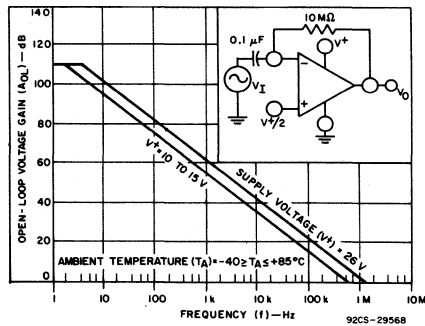


Fig.9 - Open-loop frequency response.

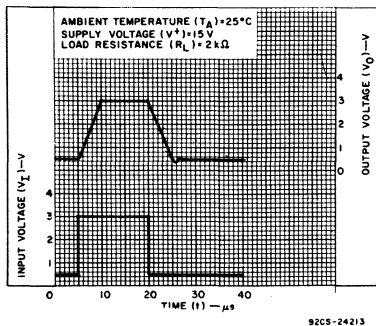


Fig.10 - Voltage follower pulse response.

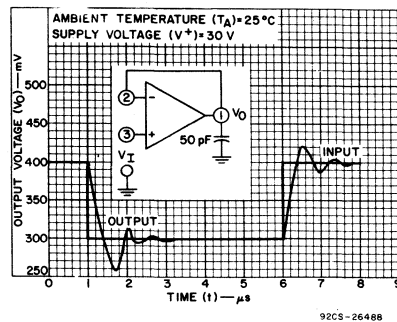


Fig.11 - Voltage follower pulse response (small signal).

Linear Integrated Circuits

CA158, CA158A, CA258, CA258A, CA358, CA358A, CA2904 Types

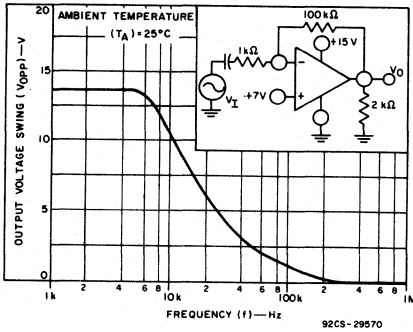


Fig. 12 - Large-signal frequency response.

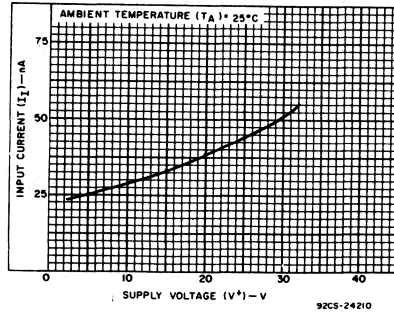


Fig. 13 - Input current as a function of supply voltage.

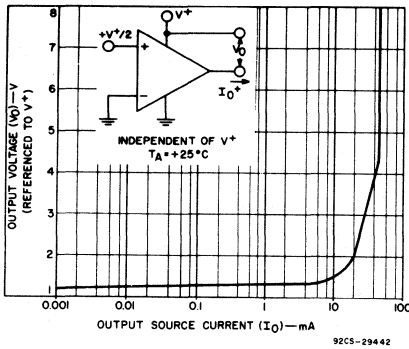


Fig. 14 - Output source current characteristics.

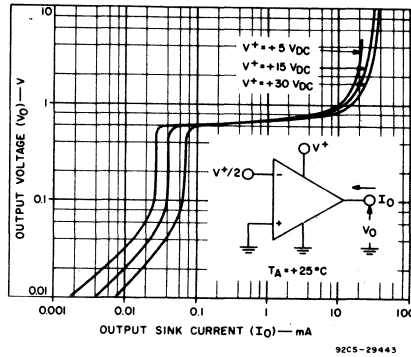


Fig. 15 - Output sink current characteristics.

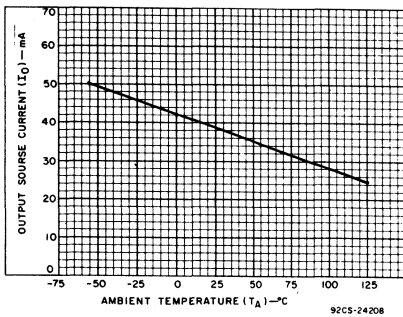


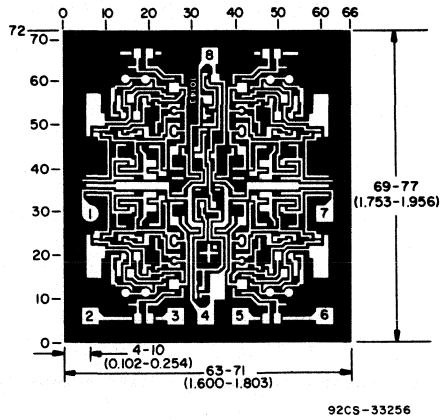
Fig. 16 - Output current as a function of ambient temperature.

ORDERING INFORMATION

These packages are identified by Suffix Letters indicated in the chart shown below. When ordering these devices, it is important that the appropriate suffix letter be affixed to the type number of the device required.

PACKAGE	SUFFIX LETTERS	TYPES
8-Lead Dual-In-Line Plastic with	E	CA158, A CA258, A CA358, A CA2904
8-Lead TO-5 Style with Standard Leads	T	CA158, A CA258, A CA358, A
8-Lead TO-5 Style with Dual-In-Line Formed Leads	S	CA158, A CA258, A CA358, A

CA158, CA158A, CA258, CA258A, CA358, CA358A, CA2904 Types



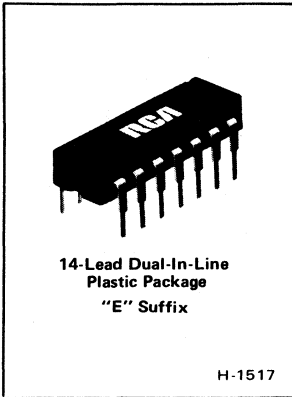
Dimensions and pad layout for CA358H..

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

The photographs and dimensions represent a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

Linear Integrated Circuits

CA124, CA224, CA324 Types



Quad Operational Amplifiers

For Commercial, Industrial, and Military Applications

Features:

- Operation from single or dual supplies
- Unity-gain bandwidth 1 MHz (typ.)
- DC voltage gain 100 dB (typ.)
- Input bias current 45 nA (typ.)
- Input offset voltage 2 mV (typ.)
- Input offset current 5 nA (typ.) for CA224, CA324
3 nA (typ.) for CA124
- Replacement for industry types 124, 224, 324

The RCA-CA124, -CA224, and -CA324 consist of four independent, high-gain operational amplifiers on a single monolithic substrate. An on-chip capacitor in each of the amplifiers provides frequency compensation for unity gain. These devices are designed specifically to operate from either single or dual supplies, and the differential voltage range is equal to the power-supply voltage. Low power drain and an input common-mode voltage range of from 0 V to $V^+ - 1.5$ V (single-supply operation) make the CA124, CA224, and CA324 suitable for battery operation.

Applications

- Summing amplifiers
- Multivibrators
- Oscillators
- Transducer amplifiers
- DC gain blocks

The CA124, CA224, and CA324 are supplied in a 14-lead dual-in-line plastic package (E suffix). The CA324 is also available in chip form (H suffix).

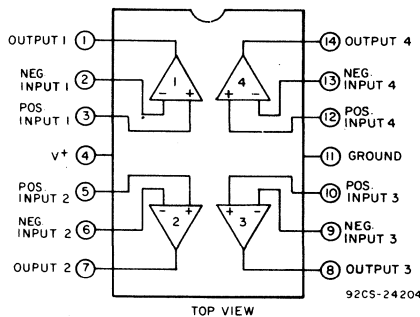


Fig. 1 - Functional diagram.

Operational Amplifiers

CA124, CA224, CA324 Types

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

SUPPLY VOLTAGE	32 V or ± 16 V
DIFFERENTIAL INPUT VOLTAGE	± 32 V
INPUT VOLTAGE	-0.3 V to +32 V
INPUT CURRENT ($V_I < -0.3$ V) [†]	50 mA
OUTPUT SHORT CIRCUIT TO GROUND ($V^+ \leq 15$ V)*	Continuous
DEVICE DISSIPATION:	
Up to $T_A = 55^\circ\text{C}$	750 mW
Above $T_A = 55^\circ\text{C}$	derate linearly at 6.67 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:	
Operating	-55 to +125 $^\circ\text{C}$
Storage	-65 to +150 $^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 \pm 1/32 in. (1.59 \pm 0.79 mm)	
from case for 10 seconds max.	+265 $^\circ\text{C}$

*The maximum output current is approximately 40 mA independent of the magnitude of V^+ . Continuous short circuits at $V^+ > 15$ V can cause excessive power dissipation and eventual destruction. Short circuits from the output to V^+ can cause overheating and eventual destruction of the device.

†This input current will only exist when the voltage at any of the input leads is driven negative. This current is due to the collector-base junction of the input p-n-p transistors becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also lateral n-p-n parasitic transistor action on the IC chip. This transistor action can cause the output voltages of the amplifiers to go to the V^+ voltage level (or to ground for a large overdrive) for the time duration that an input is driven negative. This transistor action is not destructive and normal output states will re-establish when the input voltage, which was negative, again returns to a value greater than -0.3 V dc.

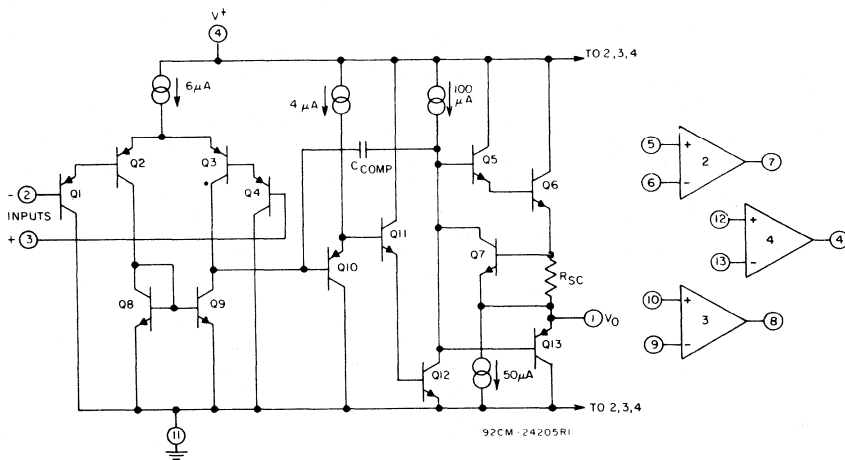


Fig. 2—Schematic diagram—one of four operational amplifiers.

Linear Integrated Circuits

CA124, CA224, CA324 Types

ELECTRICAL CHARACTERISTICS (Values Apply For Each Operational Amplifier)

CHARACTERISTIC	TEST CONDITIONS Supply Voltage (V^+) = 5 V Unless Otherwise Specified	CA124 LIMITS			UNITS
		Min.	Typ.	Max.	
$T_A = 25^\circ\text{C}$					
Input Offset Voltage, V_{IO}	Note 3	–	2	5	mV
Output Voltage Swing, V_{OPP}	$R_L = 2\text{ k}\Omega$	0	–	$V^+ - 1.5$	V
Input Common-Mode Voltage Range, V_{ICR}	Note 2, $V^+ = 30\text{ V}$	0	–	$V^+ - 1.5$	V
Input Offset Current, I_{IO}	$I_1^+ - I_1^-$	–	3	30	nA
Input Bias Current, I_{IB}	I_1^+ or I_1^- , Note 1	–	45	150	nA
Output Current (Source), I_O	$V_1^+ = +1\text{ V}$, $V_1^- = 0\text{ V}$, $V^+ = 15\text{ V}$	20	40	–	mA
Output Current (Sink), I_O	$V_1^+ = 0\text{ V}$, $V_1^- = 1\text{ V}$, $V^+ = 15\text{ V}$	10	20	–	mA
	$V_1^+ = 0\text{ V}$, $V_1^- = 1\text{ V}$, $V_O = 200\text{ mV}$	12	50	–	μA
Large-Signal Voltage Gain, A	$R_L \geq 2\text{ k}\Omega$, $V^+ = 15\text{ V}$ (For large V_O swing)	94	100	–	dB
Common-Mode Rejection Ratio, CMRR	DC	70	85	–	dB
Power Supply Rejection Ratio, PSRR	DC	65	100	–	dB
Amplifier-to-Amplifier Coupling	f = 1 to 20 kHz (Input referred)	–	–120	–	dB
$T_A = -55\text{ to }+125^\circ\text{C}$					
Input Offset Voltage, V_{IO}	Note 3	–	–	7	mV
Temperature Coefficient of Input Offset Voltage, αV_{IO}	$R_s = 0$	–	7	–	$\mu\text{V}/^\circ\text{C}$
Input Offset Current, I_{IO}	$I_1^+ - I_1^-$	–	–	100	nA
Temperature Coefficient of Input Offset Current, αI_{IO}		–	10	–	$\text{pA}/^\circ\text{C}$
Input Bias Current, I_{IB}	I_1^+ or I_1^-	–	–	300	nA
Supply Current, I^+	$R_L = \infty$ On All Ampl.	–	0.8	2	mA
Input Common-Mode Voltage Range, V_{ICR}	$V^+ = 30\text{ V}$	0	–	$V^+ - 2$	V
Large-Signal Voltage Gain, A	$R_L \geq 2\text{ k}\Omega$, $V^+ = 15\text{ V}$ (For large V_O swing)	88	–	–	dB
Output Voltage Swing:	$R_L = 2\text{ k}\Omega$, $V^+ = 30\text{ V}$	26	–	–	V
Low-Level, V_{OL}	$R_L = 10\text{ k}\Omega$	–	5	20	mV
Output Current:	$V_1^+ = 1\text{ V}_{DC}$, $V_1^- = 0$, $V^+ = 15\text{ V}$	10	20	–	mA
Sink, I_O	$V_1^- = 1\text{ V}_{DC}$, $V_1^+ = 0$, $V^+ = 15\text{ V}$	5	8	–	mA
Differential Input Voltage	Note 2	–	–	V^+	V

NOTE 1: Due to the p-n-p input stage the direction of the input current is out of the IC. No loading change exists on the input lines because this current is essentially constant, independent of the state of the output.

NOTE 2: The input signal voltages and the input common-mode voltage should not be allowed to go negative by more than 0.3 V. The positive limit of the common-mode voltage range is $V^+ - 1.5\text{ V}$, but either or both inputs can go to +32 V without damage.

NOTE 3: $V_O = 1.4\text{ V}_{DC}$, $R_s = 0\ \Omega$ with V^+ from 5 V to 30 V; and over the full input common-mode voltage range (0 V to $V^+ - 1.5\text{ V}$).

CA124, CA224, CA324 Types

ELECTRICAL CHARACTERISTICS (Values apply for each operational amplifier)

CHARACTERISTIC	TEST CONDITIONS	CA224, CA324 LIMITS			UNITS
		Supply Voltage (V^+) = 5 V Unless Otherwise Specified	Min.	Typ.	
$T_A = 25^\circ\text{C}$					
Input Offset Voltage, V_{IO}	Note 3	–	2	7	mV
Output Voltage Swing, V_{OPP}	$R_L = 2\text{ k}\Omega$	0	–	$V^+ - 1.5$	V
Input Common-Mode Voltage Range, V_{ICR}	Note 2, $V^+ = 30\text{ V}$	0	–	$V^+ - 1.5$	V
Input Offset Current, I_{IO}	$I_1^+ - I_1^-$	–	5	50	nA
Input Bias Current, I_{IB}	I_1^+ or I_1^- , Note 1	–	45	250	nA
Output Current (Source), I_O	$V_1^+ = +1\text{ V}, V_1^- = 0\text{ V},$ $V^+ = 15\text{ V}$	20	40	–	mA
Output Current (Sink), I_O	$V_1^+ = 0\text{ V}, V_1^- = 1\text{ V}, V^+ = 15\text{ V}$	10	20	–	mA
	$V_1^+ = 0\text{ V}, V_1^- = 1\text{ V},$ $V_O = 200\text{ mV}$	12	50	–	μA
Large-Signal Voltage Gain, A	$R_L \geq 2\text{ k}\Omega, V^+ = 15\text{ V}$ (For large V_O swing)	88	100	–	dB
Common-Mode Rejection Ratio, CMRR	DC	65	70	–	dB
Power Supply Rejection Ratio, PSRR	DC	65	100	–	dB
Amplifier-to-Amplifier Coupling	$f = 1\text{ to }20\text{ kHz}$ (Input referred)	–	–120	–	dB
$T_A = -40\text{ to }+85^\circ\text{C}$ (CA224), $T_A = 0\text{ to }70^\circ\text{C}$ (CA324)					
Input Offset Voltage, V_{IO}	Note 3	–	–	9	mV
Temperature Coefficient of Input Offset Voltage, $\propto V_{IO}$	$R_s = 0$	–	7	–	$\mu\text{V}/^\circ\text{C}$
Input Offset Current, I_{IO}	$I_1^+ - I_1^-$	–	–	150	nA
Temperature Coefficient of Input Offset Current, $\propto I_{IO}$		–	10	–	$\text{pA}/^\circ\text{C}$
Input Bias Current, I_{IB}	I_1^+ or I_1^-	–	–	500	nA
Supply Current, I^+	$R_L = \infty$ On All Ampl.	–	0.8	2	mA
Input Common-Mode Voltage Range, V_{ICR}	$V^+ = 30\text{ V}$	0	–	$V^+ - 2$	V
Large-Signal Voltage Gain, A	$R_L \geq 2\text{ k}\Omega, V^+ = 15\text{ V}$ (For large V_O swing)	83	–	–	dB
	Output Voltage Swing:				
High-Level, V_{OH}	$R_L = 2\text{ k}\Omega, V^+ = 30\text{ V}$	26	–	–	V
	$R_L = 10\text{ k}\Omega$	27	28	–	
Low-Level, V_{OL}	$R_L = 10\text{ k}\Omega$	–	5	20	mV
Output Current:					
Source, I_O	$V_1^+ = 1\text{ V}_{DC}, V_1^- = 0,$ $V^+ = 15\text{ V}$	10	20	–	mA
Sink, I_O	$V_1^- = 1\text{ V}_{DC}, V_1^+ = 0,$ $V^+ = 15\text{ V}$	5	8	–	mA
Differential Input Voltage	Note 2	–	–	V^+	V

NOTE 1: Due to the p-n-p input stage the direction of the input current is out of the IC. No loading change exists on the input lines because this current is essentially constant, independent of the state of the output.

NOTE 2: The input signal voltages and the input common-mode voltage should not be allowed to go negative by more than 0.3 V. The positive limit of the common-mode voltage range is $V^+ - 1.5\text{ V}$, but either or both inputs can go to +32 V without damage.

NOTE 3: $V_O = 1.4\text{ V}_{DC}$, $R_s = 0\ \Omega$ with V^+ from 5 V to 30 V; and over the full input common-mode voltage range (0 V to $V^+ - 1.5\text{ V}$).

Linear Integrated Circuits

CA124, CA224, CA324 Types

TYPICAL CHARACTERISTICS CURVES

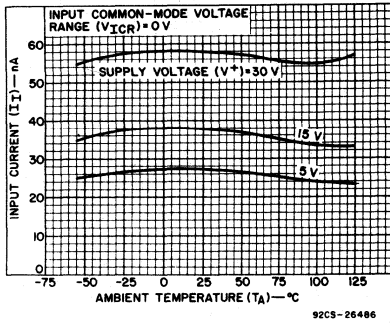


Fig. 3—Input current vs. ambient temperature.

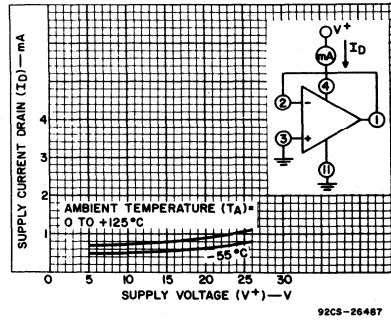


Fig. 4—Supply current drain vs. supply voltage.

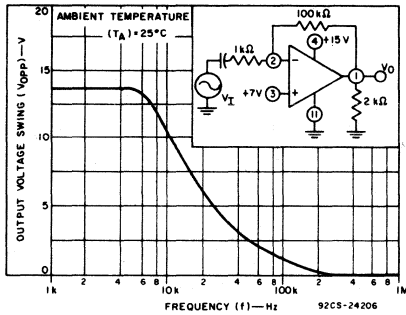


Fig. 5—Large-signal frequency response.

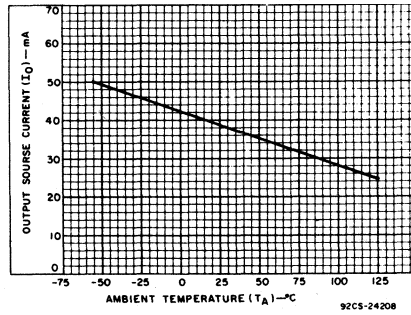


Fig. 6—Output current vs. ambient temperature.

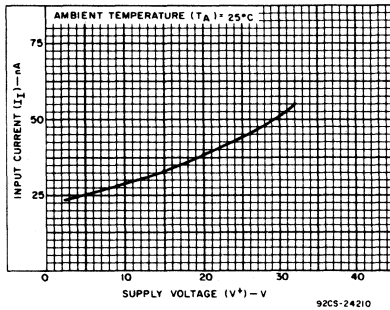


Fig. 7—Input current vs. supply voltage.

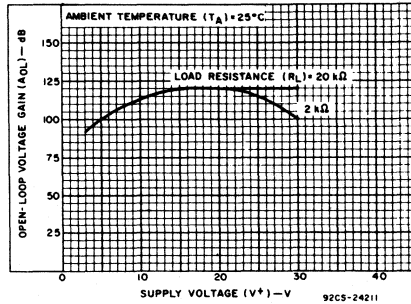


Fig. 8—Voltage gain vs. supply voltage.

Operational Amplifiers CA124, CA224, CA324 Types

TYPICAL CHARACTERISTICS CURVES (CONT'D)

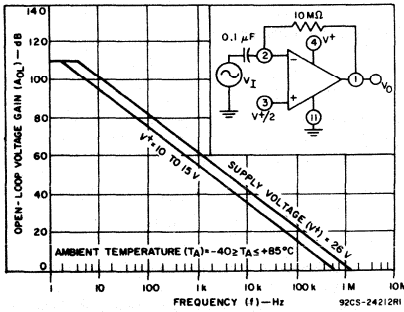


Fig. 9—Open-loop frequency response.

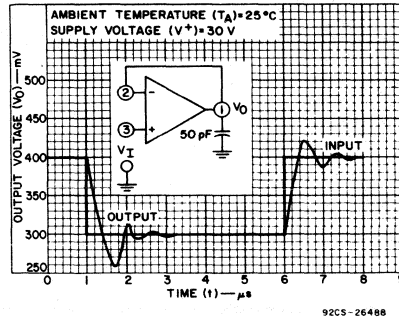


Fig. 10—Voltage follower pulse response (small signal).

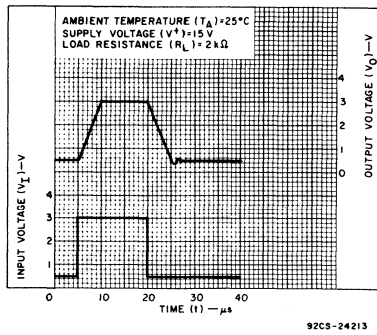
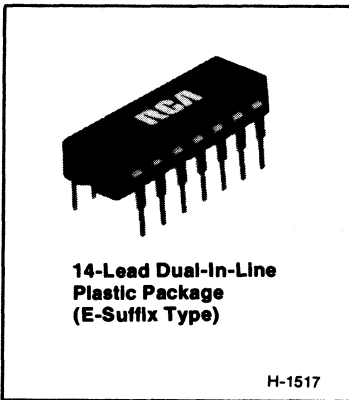


Fig. 11—Voltage follower pulse response.

CA3401E



14-Lead Dual-In-Line Plastic Package (E-Suffix Type)

H-1517

Quad Single-Supply Operational Amplifier

For Automotive Electronics and Industrial Control Systems

"E" Suffix Types — Standard Dual-In-Line Plastic Package

Features:

- Single-supply operation — +5 V to +18 Vdc
- Internally compensated
- Wide unity-gain bandwidth — 5 MHz typ.
- Low input bias current — 50 nA typ.
- High open-loop gain — 2000 V/V typ.

Applications:

- Automotive
- Constant-Current Sources
- Multivibrators
- Sample and Hold
- Square-Wave Generator
- Oscillators
- Tachometers
- Active Filters
- Multi-Channel Amplifiers
- Summing Amplifiers

The RCA-3401 is a high-gain monolithic quad operational amplifier designed specifically for applications using a single positive power supply. No external compensation is necessary. Closed-loop stability in each of the four independent amplifiers is maintained by a 3-pF on-chip capacitor. The CA3401 is ideally suited for applications in industrial control systems, automotive electronics, and general purpose amplifiers, e.g. oscillators, tachometers, active filters, and multichannel amplifiers.

The CA3401 is supplied in a 14-lead dual-in-line plastic package (E suffix), and is also available in chip form (H suffix). It is a direct replacement for the Motorola MC3401P, and is pin-compatible with the Motorola MC3301P and the National Semi-conductor LM3900N. The CA3401 can be operated over the temperature range of -55 to +125°C, although the limit values of certain specified electrical characteristics apply only over the range of 0 to +75°C.

MAXIMUM RATINGS, Absolute-Maximum Values at TA = 25°C

DC SUPPLY VOLTAGE	+18 V
INPUT SIGNAL CURRENT	5 mA
DEVICE DISSIPATION:	
Up to TA = 25°C	625 mW
Above TA = 25°C	Derate linearly 5 mW/°C
AMBIENT TEMPERATURE RANGE:	
Operating	-55 to +125°C
Storage	-65 to +150°C
LEAD TEMPERATURE (During soldering):	
At distance 1/16 ± 1/32 inch (1.59 ± 0.79 mm) from case for 10 seconds max.	300°C

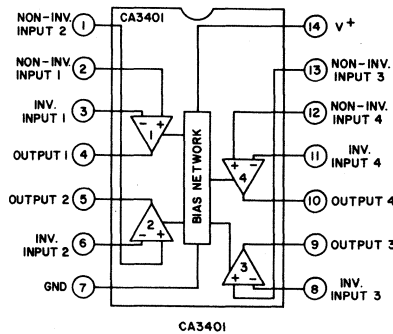


Fig. 1 - Block diagram of CA3401.

ELECTRICAL CHARACTERISTICS AT $T_A = 25^\circ\text{C}$, $V^+ = 15\text{ V}$ (Unless Indicated Otherwise)

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
STATIC					
Output Voltage:		13.5	14.2	—	V
High, V_{OH}		—	0.03	0.1	
Low, V_{OL}		—	—	—	
Max. Undistorted Output Swing, V_{OP-P}	$0^\circ\text{C} < T_A < 75^\circ\text{C}$	10	13.5	—	
Output Current:		5	10	—	mA
Source, I_{SOURCE}		0.5	1	—	
Sink, I_{SINK}		—	—	—	
Total Quiescent Current: I_Q		—	6.9	10	mA
Noninverting inputs open		—	7.8	14	
Noninverting inputs grounded		—	—	—	
Input Bias Current, I_{IB}	$R_L = \infty$ $T_A = 25^\circ\text{C}$	—	50	300	nA
	$R_L = \infty$ $0^\circ\text{C} \leq T_A \leq 75^\circ\text{C}$	—	—	500	
DYNAMIC					
Open-Loop Voltage Gain, A_{OL}	$T_A = 25^\circ\text{C}$	1000	2000	—	V/V
	$0^\circ\text{C} \leq T_A \leq 75^\circ\text{C}$	800	—	—	
Input Resistance, R_i		0.1	1	—	$M\Omega$
Slew Rate, SR	$C_L = 100\text{ pF}$, $R_L = 5\text{ k}\Omega$	—	0.6	—	$\text{V}/\mu\text{s}$
Unity Gain Bandwidth, BW		—	5	—	MHz
Phase Margin, ϕ		—	70	—	Degrees
Power Supply Rejection	$f = 100\text{ Hz}$	—	55	—	dB
Channel Separation, e_{O1}/e_{O2}	$f = 1\text{ kHz}$	—	65	—	dB

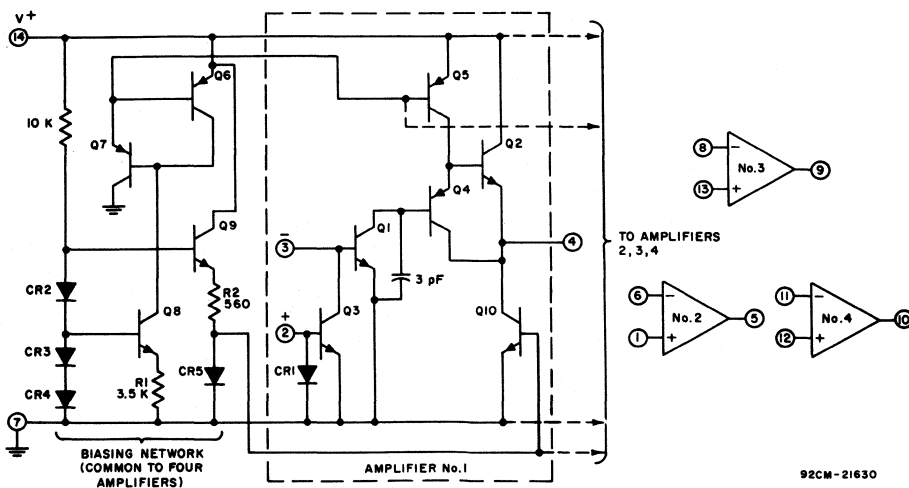


Fig.2 – Schematic diagram of CA3401.

CA3401E

TEST CIRCUITS

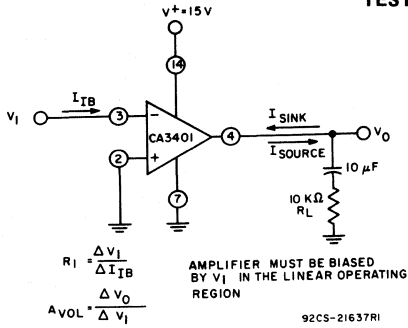


Fig. 3 - Open-loop gain and input resistance, input bias current and output current test circuit.

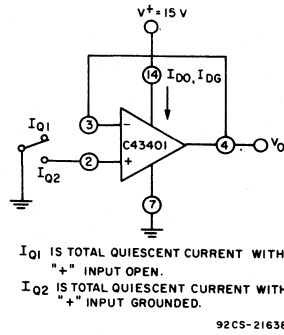


Fig. 4 - Quiescent power supply current test circuit.

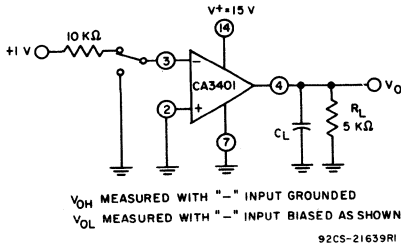


Fig. 5 - Output voltage swing test circuit.

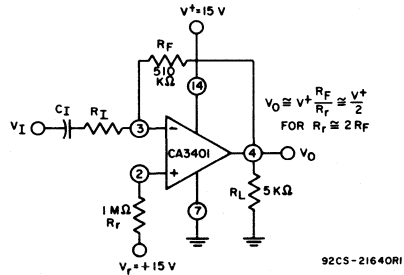


Fig. 6 - Peak-to-peak output voltage test circuit.

TYPICAL CHARACTERISTIC CURVES

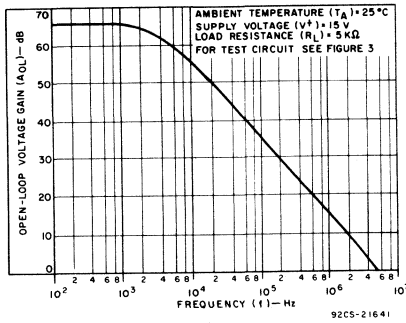


Fig. 7 - Open-loop voltage gain vs. frequency.

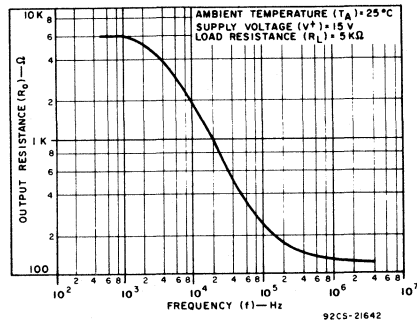


Fig. 8 - Output resistance vs. frequency.

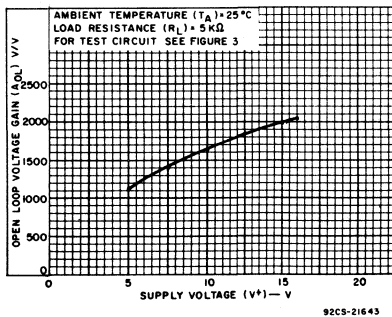


Fig. 9 - Open-loop voltage gain vs. supply voltage.

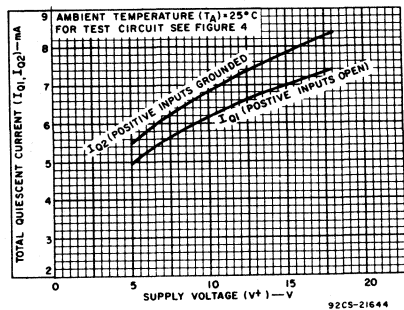


Fig. 10 - Supply current vs. supply voltage.

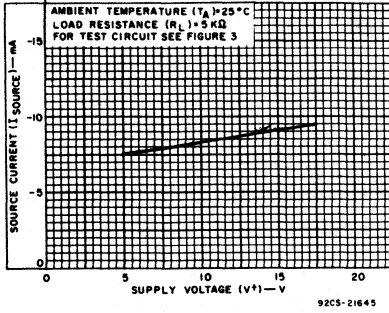


Fig. 11 — Source current vs. supply voltage.

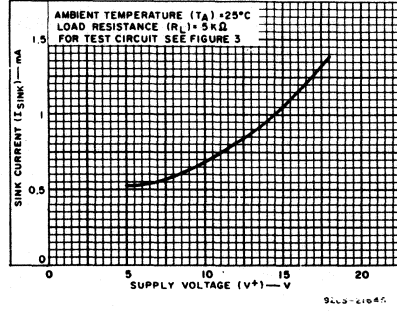
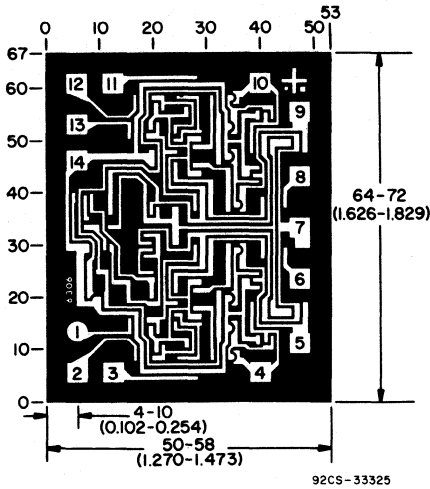


Fig. 12 — Sink current vs. supply voltage.



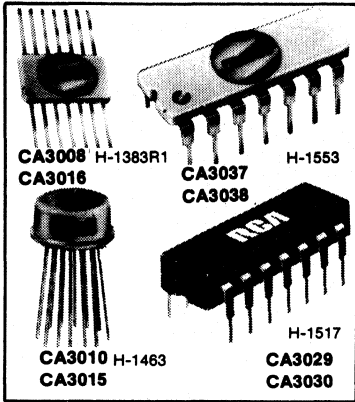
Dimensions and pad layout for CA3401H

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

The photographs and dimensions represent a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

CA3008, CA3010, CA3015, CA3016, CA3029, CA3030, CA3037, CA3038

Operational Amplifiers



Features:

- All types are electrically identical within their voltage groups
- For use in telemetry, data-processing, instrumentation, and communication equipment
- Built-in temperature stability from -55°C to $+125^{\circ}\text{C}$ for flat pack, TO-5 style, and ceramic dual-in-line packages; 0°C to $+70^{\circ}\text{C}$ for plastic dual-in-line packages

6-Volt Types

- CA3008
- CA3010
- CA3029

- CA3037

12-Volt Types

- CA3016
- CA3015
- CA3030

- CA3038

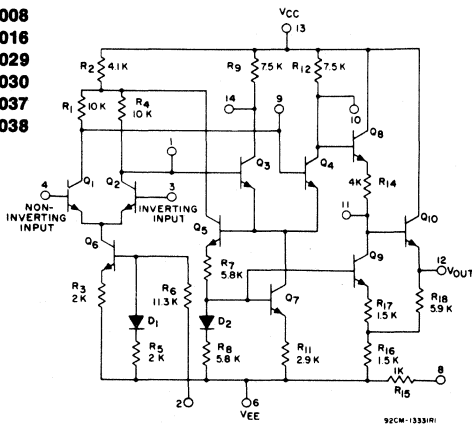
Package

- 14-Lead Flat Pack
- 12-Lead TO-5 Style
- 14-Lead Plastic Dual-In-Line (TO-116)
- 14-Lead Ceramic Dual-In-Line (TO-116)

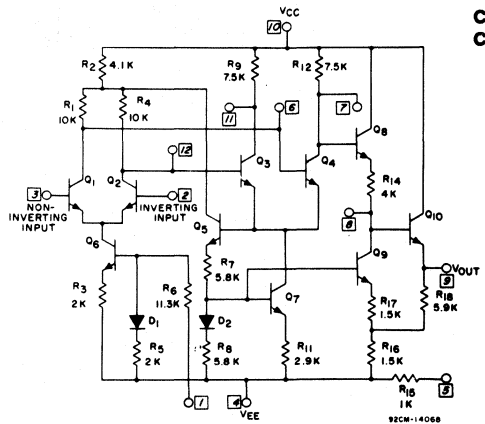
Applications:

- Narrow-band and band-pass amplifier
- Operational functions
- Feedback amplifier
- DC and video amplifier
- Multivibrator
- Oscillator
- Comparator
- Servo driver
- Scaling adder
- Balanced modulator-driver

CA3008
CA3016
CA3029
CA3030
CA3037
CA3038



CA3010
CA3015



Schematic diagrams.

Operational Amplifiers

CA3008, CA3010, CA3015, CA3016, CA3029, CA3030, CA3037, CA3038

ABSOLUTE-MAXIMUM VOLTAGE AND CURRENT LIMITS, T_A = 25°C

Voltage or current limits shown for each terminal can be applied under the indicated voltage or other circuit conditions for other terminals

All voltages are with respect to ground (common terminal of Positive and Negative DC Supplies)

Terminal		Voltage or Current Limits		Circuit Conditions		
CA3010	CA3008 CA3029 CA3037	Nega- tive	Posi- tive	Terminal		Voltage
	12			1	DO NOT APPLY VOLTAGE FROM AN EXTERNAL SOURCE TO THIS TERMINAL	
				CA3010	CA3008 CA3029 CA3037	
1	2	-8 V	0 V	4 10	6 13	-8 +6
2	3	-4 V	+1 V	1 3 4 10	2 4 6 13	0 0 -6 +6
3	4	-4 V	+1 V	1 2 4 10	2 3 6 13	0 0 -6 +6
	5	NO CONNECTION				
4	6	-10 V	0 V	1 10	2 13	0 +6
	7	NO CONNECTION				
5	8	DO NOT APPLY VOLTAGE FROM AN EXTERNAL SOURCE TO THIS TERMINAL				
6	9	DO NOT APPLY VOLTAGE FROM AN EXTERNAL SOURCE TO THIS TERMINAL				
7	10	0 V	+7 V	1 4 10	2 6 13	0 -6 +6
8	11	DO NOT APPLY VOLTAGE FROM AN EXTERNAL SOURCE TO THIS TERMINAL				
9	12	30 mA		4 10	6 13	-6 +6
				200 Ω Between Terminals 6 & 12 (CA3008, CA3029, CA3037) 4 & 9 (CA3010)		
10	13	0 V	+10 V	1 4	2 6	0 -6
11	14	0 V	+7 V	1 4 10	2 6 13	0 -6 +6
CASE		Internally connected to Terminal No.6, CA3008, CA3029, CA3037 No.4, CA3010 (Substrate) DO NOT GROUND				

Terminal		Voltage or Current Limits		Circuit Conditions		
CA3015	CA3016 CA3030 CA3038	Nega- tive	Posi- tive	Terminal		Voltage
	12			1	DO NOT APPLY VOLTAGE FROM AN EXTERNAL SOURCE TO THIS TERMINAL	
				CA3015	CA3016 CA3030 CA3038	
1	2	-16 V	0 V	4 10	6 13	-16 +12
2	3	-8 V	+1 V	1 3 4 10	2 4 6 13	0 0 -12 +12
3	4	-8 V	+1 V	1 2 4 10	2 3 6 13	0 0 -12 +12
	5	NO CONNECTION				
4	6	-20 V	0 V	1 10	2 13	0 +12
	7	NO CONNECTION				
5	8	DO NOT APPLY VOLTAGE FROM AN EXTERNAL SOURCE TO THIS TERMINAL				
6	9	DO NOT APPLY VOLTAGE FROM AN EXTERNAL SOURCE TO THIS TERMINAL				
7	10	0 V	+14 V	1 4 10	2 6 13	0 -12 +12
8	11	DO NOT APPLY VOLTAGE FROM AN EXTERNAL SOURCE TO THIS TERMINAL				
9	12	30 mA		4 10	6 13	-12 +12
				400 Ω Between Terminals 6 & 12 (CA3016, CA3030, CA3038) 4 & 9 (CA3015)		
10	13	0 V	+20 V	1 4	2 6	0 -12
11	14	0 V	+14 V	1 4 10	2 6 13	0 -12 +12
CASE		Internally connected to Terminal No.6, CA3016, CA3030, CA3038 No.4, CA3015 (Substrate) DO NOT GROUND				

CA3008	CA3010
CA3016	CA3015
CA3037	CA3038
	CA3029 CA3030

CA3016	CA3015	CA3008	CA3010
CA3030	CA3038	CA3029	CA3037

OPERATING TEMPERATURE RANGE . . . -55°C to +125°C
 STORAGE TEMPERATURE RANGE . . . -65°C to +200°C

0°C to +70°C
 -25°C to +85°C
 MAXIMUM SIGNAL VOLTAGE -8 V to +1 V
 MAXIMUM DEVICE DISSIPATION 600 mW 300 mW

Linear Integrated Circuits

CA3008, CA3010, CA3015, CA3016, CA3029, CA3030, CA3037, CA3038

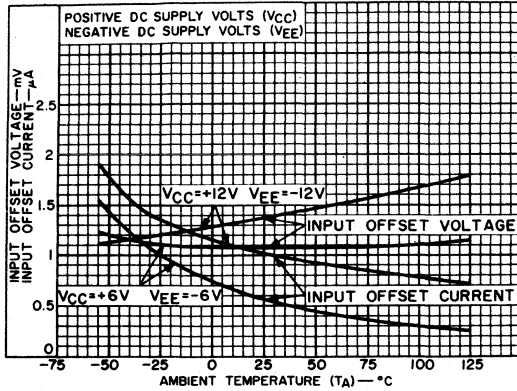
ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

Characteristics	Symbols	Special Test Conditions Terminal No.8 (CA3008, CA3016, CA3029, CA3030, CA3037, CA3038) Terminal No.5 (CA3010, CA3015) Not Connected Unless Otherwise Specified	Test Cir- cuit	CA3008 CA3010 CA3029 CA3037			CA3016 CA3015 CA3030 CA3038			Units	Typical Charac- teristic Curves	
				Fig.	Min.	Typ.	Max.	Min.	Typ.			Max.
STATIC CHARACTERISTICS:												
Input Offset Voltage	V_{IO}	$V_{CC} = +6V, V_{EE} = -6V$ $= +12V = -12V$	4	-	1.08	5	-	-	1.37	5	mV	2
Input Offset Current	I_{IO}	$= +6V = -6V$ $= +12V = -12V$	5	-	0.54	5	-	-	1.07	5	μA	2
Input Bias Current	I_I	$= +6V = -6V$ $= +12V = -12V$	5	-	5.3	12	-	-	9.6	24	μA	3
Input Offset Voltage Sensitivity:	Positive	$\Delta V_{IO}/\Delta V_{CC}$	4	-	0.10	1	-	-	0.096	0.5	mV/V	none
	Negative	$\Delta V_{IO}/\Delta V_{EE}$		-	0.26	1	-	-	0.156	0.5		
Device Dissipation	P_T	$= +6V = -6V$ $= +12V = -12V$	4	-	30	-	-	-	175	-	mW	none
		$\text{[5] shorted to [9]}$ $V_{CC} = +6V, V_{EE} = -6V$ 8 shorted to 12 $V_{CC} = +12V, V_{EE} = -12V$		-	102	-	-	-	500	-		
DYNAMIC CHARACTERISTICS: All tests at $f = 1\text{ kHz}$ except BW_{OL}												
Open-Loop Differential Voltage Gain	A_{OL}	$V_{CC} = +6V, V_{EE} = -6V$ $= +12V = -12V$	8	57	60	-	-	66	70	-	dB	6 & 7
Open-Loop Bandwidth at -3 dB Point	BW_{OL}	$= +6V = -6V$ $= +12V = -12V$	8	200	300	-	-	200	320	-	kHz	6 & 7
Common-Mode Rejection Ratio	CMR	$V_{CC} = +6V, V_{EE} = -6V$ $= +12V = -12V$	11	70	94	-	-	80	103	-	dB	12
Maximum Output-Voltage Swing	$V_{O(P-P)}$	$= +6V = -6V$ $= +12V = -12V$	8	4	6.75	-	-	12	14	-	V _{P-P}	9 & 10
Input Impedance	Z_{IN}	$= +6V = -6V$ $= +12V = -12V$	14	10	14	-	-	5	7.8	-	$k\Omega$	13
Output Impedance	Z_{OUT}	$= +6V = -6V$ $= +12V = -12V$	15	-	200	-	-	-	92	-	Ω	16
Common-Mode Input-Voltage Range	V_{CMR}	$= +6V = -6V$ $= +12V = -12V$	11	-	+0.5 -4	-	-	-	-	-	V	none

CA3008, CA3010, CA3015, CA3016, CA3029, CA3030, CA3037, CA3038 TYPICAL STATIC CHARACTERISTICS AND TEST CIRCUITS

Terminal Numbers in Circles are for CA3008, CA3016, CA3029, CA3030, CA3037, CA3038;
Italic Numbers in Square Boxes are for CA3010, CA3015

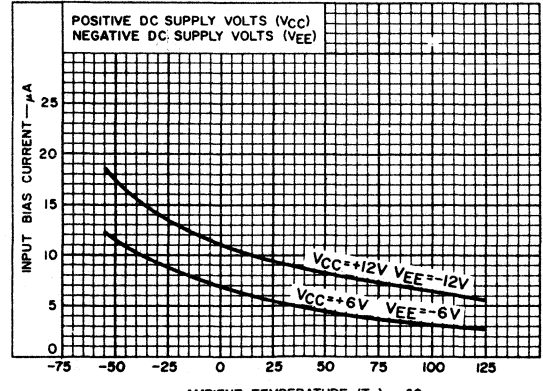
INPUT OFFSET VOLTAGE AND CURRENT



92CS-14929

Fig.2

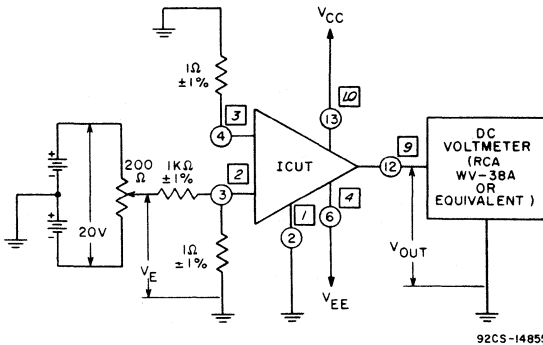
INPUT BIAS CURRENT



92CS-14932

Fig.3

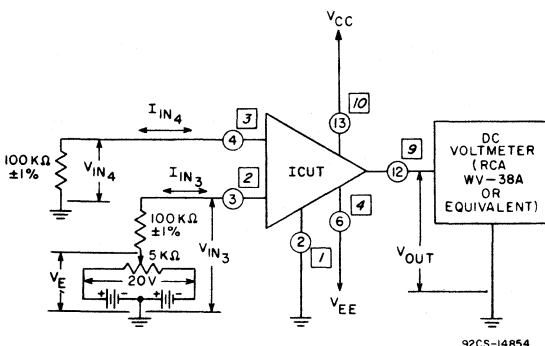
INPUT OFFSET VOLTAGE, INPUT OFFSET VOLTAGE SENSITIVITY, AND DEVICE DISSIPATION TEST CIRCUIT



92CS-14855

Fig.4

INPUT OFFSET CURRENT AND INPUT BIAS CURRENT TEST CIRCUIT



92CS-14854

Fig.5

Procedure:

Input Offset Voltage

1. Adjust V_E for a DC Output Voltage (V_{OUT}) of 0 ± 0.1 volts.
2. Measure V_E and record Input Offset Voltage in millivolts as $V_E/1000$.

Input Offset Voltage Sensitivity

1. Adjust V_E for a DC Output Voltage (V_{OUT}) of 0 ± 0.1 volts.
2. Increase $|V_{CC}|$ by 1 volt and record output voltage (V_{OUT}).
3. Decrease $|V_{CC}|$ by 1 volt and record output voltage (V_{OUT}).
4. Divide the difference between V_{OUT} measured in steps 2 and 3 by the change in V_{CC} in steps 2 and 3.

$$\frac{V_{OUT}}{V_{CC}} = \frac{V_{OUT} (\text{Step 2}) - V_{OUT} (\text{Step 3})}{2 \text{ volts}}$$

5. Refer the reading to the input by dividing by Open Loop Voltage Gain (A_{OL}).

$$V_{IO}/V_{CC} = \frac{V_{OUT}/V_{CC}}{A_{OL}}$$

6. Repeat procedures 1 through 5 for the Negative Supply (V_{EE}).
7. Device Dissipation

$$P_T = V_{CC}I_C + V_{EE}I_E$$

I_C = Direct Current into Terminal (13) or (10)

I_E = Direct Current out of Terminal (6) or (4)

Procedure:

Input Bias Current and Input Offset Current

1. Adjust V_E for $|V_{OUT}| < 0.1$ V DC.
2. Measure and record V_E and V_{IN4} .
3. Calculate the Input Bias Current using the following equation:

$$I_{I4} = \frac{V_{IN4}}{100 \text{ k}\Omega}$$

4. Calculate the Input Offset Current using the following equation:

$$I_{IO} = V_E/100 \text{ k}\Omega$$

Linear Integrated Circuits

CA3008, CA3010, CA3015, CA3016, CA3029, CA3030, CA3037, CA3038

TYPICAL DYNAMIC CHARACTERISTICS AND TEST CIRCUITS

Terminal Numbers in Circles are for CA3008, CA3016, CA3029, CA3030, CA3037, CA3038;
 Italic Numbers in Square Boxes are for CA3010, CA3015

OPEN-LOOP VOLTAGE GAIN vs. FREQUENCY
 FOR CA3008, CA3010, CA3015, CA3016,
 CA3037, CA3038

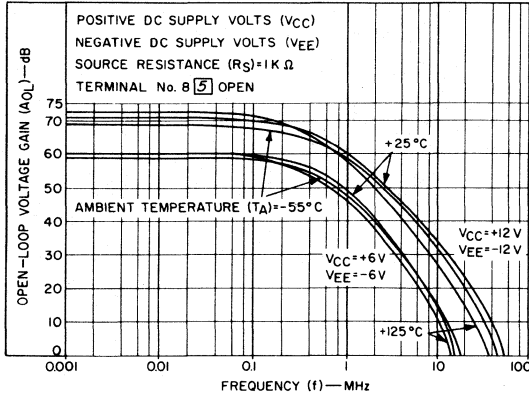


Fig. 6

OPEN-LOOP VOLTAGE GAIN vs. FREQUENCY
 FOR CA3029 AND CA3030

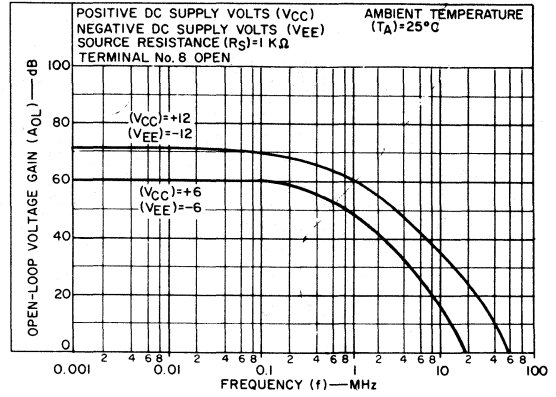
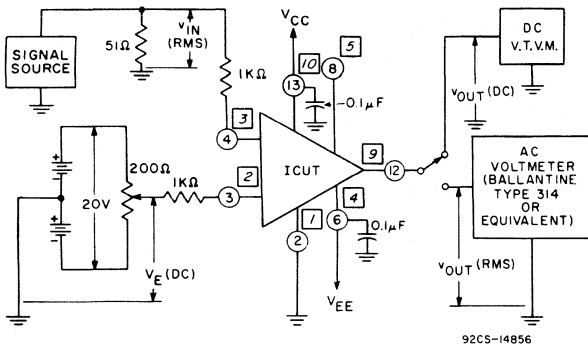


Fig. 7

OPEN-LOOP DIFFERENTIAL VOLTAGE GAIN, MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE, AND OPEN-LOOP BANDWIDTH AT -3 dB POINT TEST CIRCUIT



92CS-14856

Procedure:

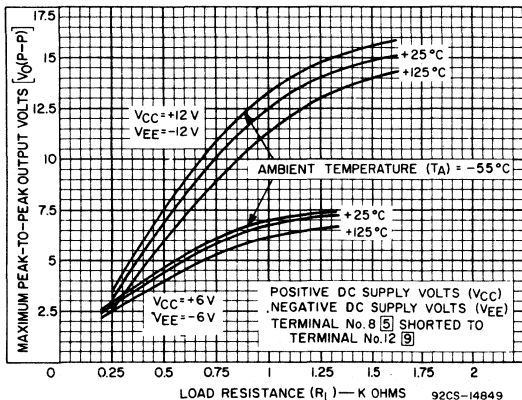
1. Adjust V_E for $V_{OUT} = \pm 0.1$ V DC.
2. Measure Open-Loop Differential Voltage Gain (A_{OL}) at $f = 1$ kHz.
3. Measure Maximum Peak-to-Peak Output Voltage at $f = 1$ kHz.
4. Measure Open-Loop Bandwidth at -3 dB Point.

$$A_{OL} = 20 \log_{10} \frac{V_{OUT}}{V_{IN}}$$

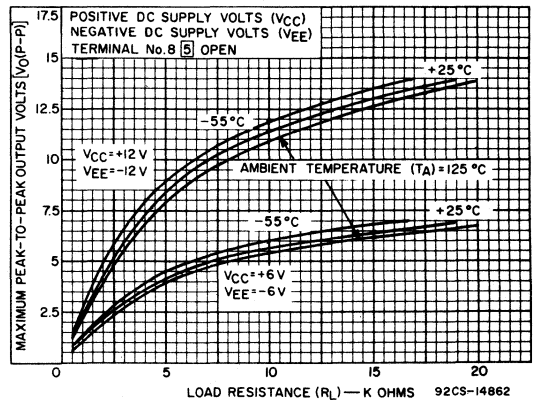
Reference Level = A_{OL} at 1 kHz.

Fig. 8

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE vs. LOAD RESISTANCE
 FOR CA3008, CA3010, CA3015, CA3016, CA3037, CA3038



(a)



(b)

Fig. 9

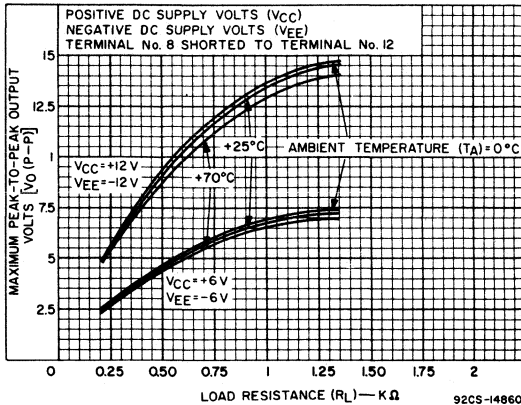
CA3008, CA3010, CA3015, CA3016, CA3029, CA3030, CA3037, CA3038

TYPICAL DYNAMIC CHARACTERISTICS AND TEST CIRCUITS

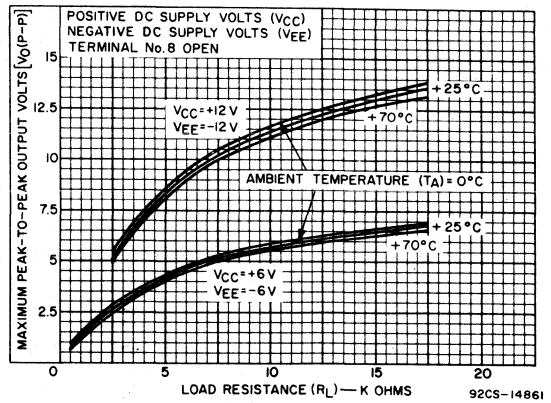
Terminal Numbers in Circles are for CA3008, CA3016, CA3029, CA3030, CA3037, CA3038;

Italic Numbers in Square Boxes are for CA3010, CA3015

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE vs. LOAD RESISTANCE FOR CA3029 AND CA3030



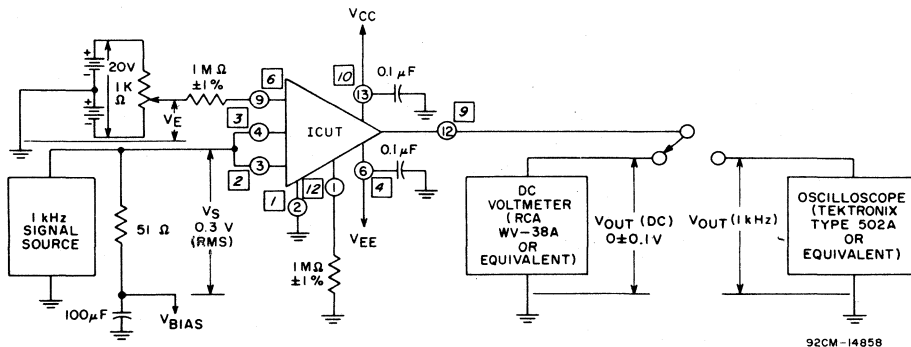
(a)



(b)

Fig.10

COMMON-MODE REJECTION RATIO AND COMMON-MODE INPUT-VOLTAGE-RANGE TEST CIRCUIT



92CM-14858

Procedures:

Common-Mode Rejection Ratio:

1. Set $V_{BIAS} = 0$. Adjust V_E for $V_{OUT(DC)} = 0 \pm 0.1$ V.
2. Apply 1-kHz sinusoidal input signal and adjust for $V_S = 0.3$ V (RMS).
3. Measure and record the RMS value of V_{OUT} . An oscilloscope is used for this measurement so that the output signal may be visually separated from noise output.
4. Calculate Common-Mode Voltage Gain:

$$A_{CM} = V_{OUT} / V_S$$

$$A_{CM} \text{ in dB} = -20 \text{ LOG}_{10} V_S / V_{OUT}$$

5. Calculate Common-Mode Rejection Ratio:

$$\text{CMR in dB} = A_{DIFF} \text{ in dB} - A_{CM} \text{ in dB.}$$

Common-Mode Input-Voltage Range:

1. Calculate and record CMR for various positive and negative values of V_{BIAS} within the maximum limits shown on Page 2. The Common-Mode Input-Voltage Range limits are those values of V_{BIAS} at which CMR is 6 dB less than that calculated in Step 5 of the procedure given above.

Fig.11

COMMON-MODE REJECTION RATIO vs. FREQUENCY

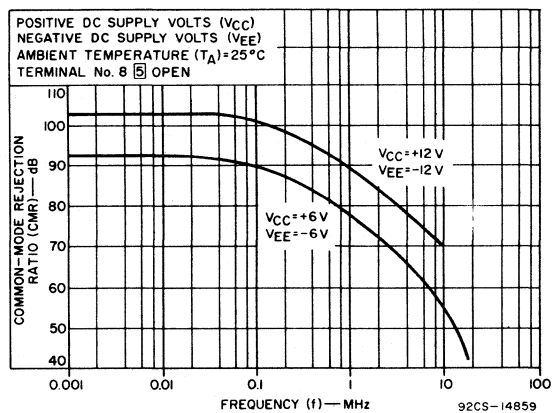


Fig.12

Linear Integrated Circuits

CA3008, CA3010, CA3015, CA3016, CA3029, CA3030, CA3037, CA3038

TYPICAL DYNAMIC CHARACTERISTICS AND TEST CIRCUITS

Terminal Numbers in Circles are for CA3008, CA3016, CA3029, CA3030, CA3037, CA3038;
 Italic Numbers in Square Boxes are for CA3010, CA3015

SINGLE-ENDED INPUT IMPEDANCE vs. TEMPERATURE

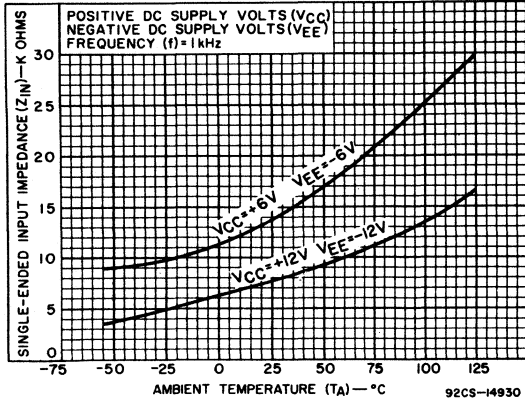


Fig.13

SINGLE-ENDED INPUT IMPEDANCE TEST CIRCUIT

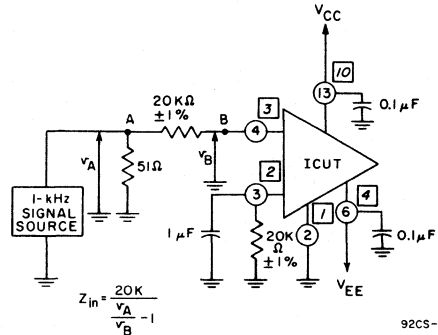
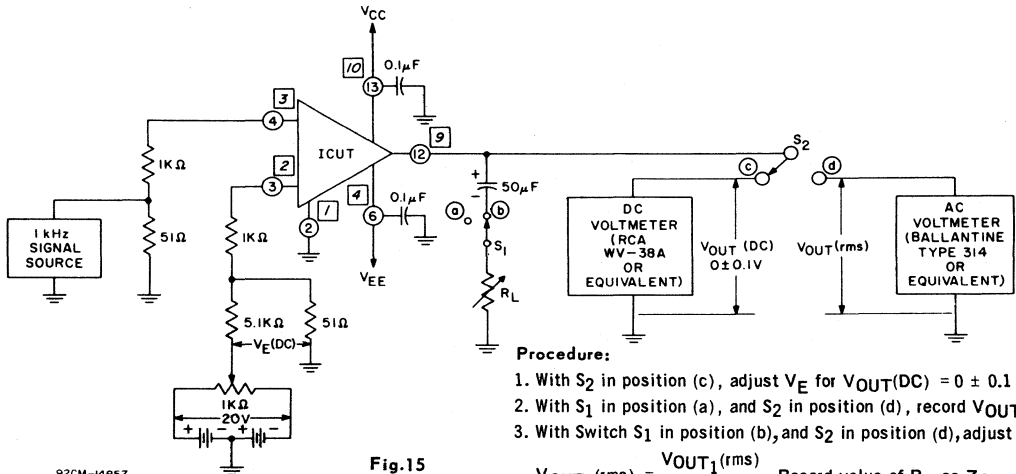


Fig.14

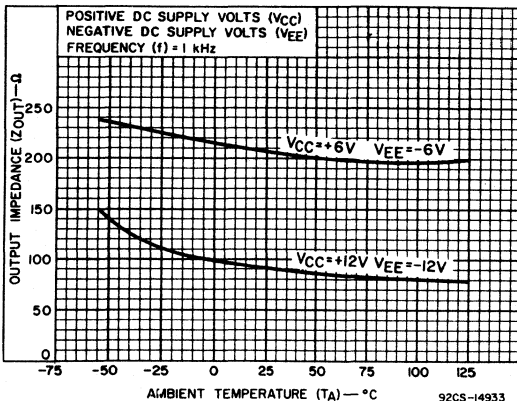
OUTPUT IMPEDANCE TEST CIRCUIT



Procedure:

1. With S_2 in position (c), adjust V_E for $V_{OUT(DC)} = 0 \pm 0.1$ volt.
2. With S_1 in position (a), and S_2 in position (d), record $V_{OUT1}(rms)$.
3. With Switch S_1 in position (b), and S_2 in position (d), adjust R_L until

$$V_{OUT2}(rms) = \frac{V_{OUT1}(rms)}{2}. \text{ Record value of } R_L \text{ as } Z_{OUT}.$$

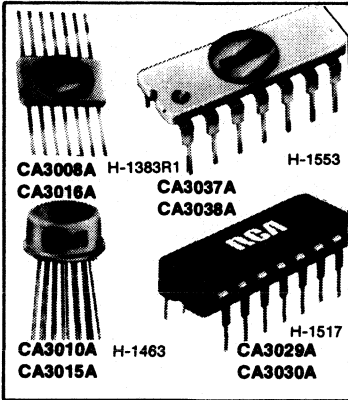


OUTPUT IMPEDANCE vs. TEMPERATURE

Fig.16

CA3008A, CA3010A, CA3015A, CA3016A, CA3029A, CA3030A, CA3037A, CA3038A

Operational Amplifiers



Features:

- These new types have all the desirable features and characteristics of their prototypes plus lower noise figures and improved input characteristics for offset voltage, offset current, bias current, and impedance
- All types are electrically identical within their voltage groups
- For use in telemetry, data-processing, instrumentation, and communication equipment
- Built-in temperature stability from -55°C to $+125^{\circ}\text{C}$ for flat pack, TO-5 style, and ceramic dual-in-line packages; 0°C to $+70^{\circ}\text{C}$ for plastic dual-in-line packages

Applications:

- Narrow-band and band-pass amplifier
- Operational functions
- Feedback amplifier
- DC and video amplifier
- Multivibrator
- Oscillator
- Comparator
- Servo driver
- Scaling adder
- Balanced modulator-driver

6-Volt Types

- CA3008A
- CA3010A
- CA3029A

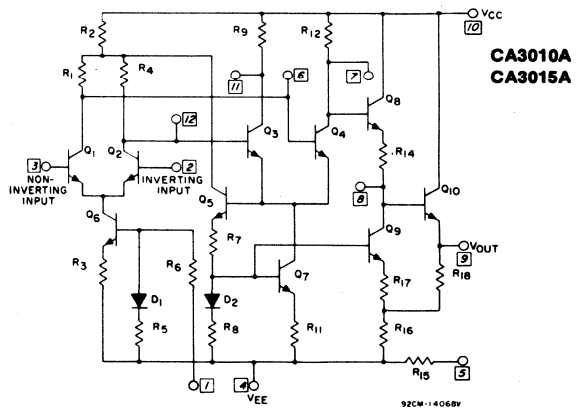
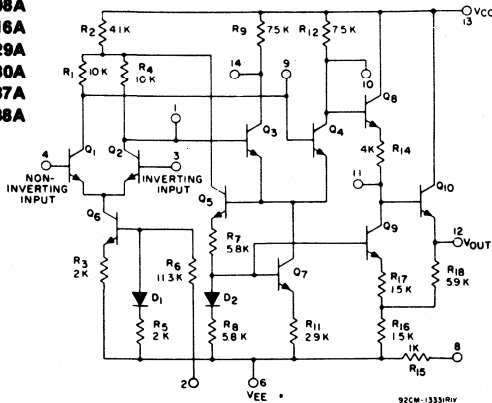
12-Volt Types

- CA3016A
- CA3015A
- CA3030A
- CA3037A
- CA3038A

Package

- 14-Lead Flat Pack
- 12-Lead TO-5 Style
- 14-Lead Plastic Dual-In-Line (TO-116)
- 14-Lead Ceramic Dual-In-Line (TO-116)

- CA3008A
- CA3016A
- CA3029A
- CA3030A
- CA3037A
- CA3038A



Schematic diagrams.

Linear Integrated Circuits

CA3008A, CA3010A, CA3015A, CA3016A, CA3029A, CA3030A, CA3037A, CA3038A

ABSOLUTE-MAXIMUM VOLTAGE AND CURRENT LIMITS, $T_A = 25^\circ\text{C}$

Voltage or current limits shown for each terminal can be applied under the indicated voltage or other circuit conditions for other terminals

All voltages are with respect to ground (common terminal of Positive and Negative DC Supplies)

Terminal		Voltage or Current Limits		Circuit Conditions		
CA3010A	CA3008A CA3029A CA3037A	Nega- tive	Posi- tive	Terminal		
	Terminal			Voltage		
12	1	DO NOT APPLY VOLTAGE FROM AN EXTERNAL SOURCE TO THIS TERMINAL				
				CA3010A	CA3008A CA3029A CA3037A	
1	2	-8 V	0 V	4 10	6 13	-8 +6
2	3	-4 V	+1 V	1 3 4 10	2 4 6 13	0 0 -6 +6
3	4	-4 V	+1 V	1 2 4 10	2 3 6 13	0 0 -6 +6
-	5	NO CONNECTION				
4	6	-10 V	0 V	1 10	2 13	0 +6
-	7	NO CONNECTION				
5	8	DO NOT APPLY VOLTAGE FROM AN EXTERNAL SOURCE TO THIS TERMINAL				
6	9	DO NOT APPLY VOLTAGE FROM AN EXTERNAL SOURCE TO THIS TERMINAL				
7	10	0 V	+7 V	1 4 10	2 6 13	0 -6 +6
8	11	DO NOT APPLY VOLTAGE FROM AN EXTERNAL SOURCE TO THIS TERMINAL				
9	12	30 mA		4 10	6 13	-6 +6
				200 Ω Between Terminals 6 & 12 (CA3008A, CA3029A, CA3037A) 4 & 9 (CA3010A)		
10	13	0 V	+10 V	1 4	2 6	0 -6
11	14	0 V	+7 V	1 4 10	2 6 13	0 -6 +6
CASE	Internally connected to Terminal No.6, CA3008A, CA3029A, CA3037A No.4, CA3010A (Substrate) DO NOT GROUND					

Terminal		Voltage or Current Limits		Circuit Conditions		
CA3015A	CA3016A CA3030A CA3038A	Nega- tive	Posi- tive	Terminal		
	Terminal			Voltage		
12	1	DO NOT APPLY VOLTAGE FROM AN EXTERNAL SOURCE TO THIS TERMINAL				
				CA3015A	CA3016A CA3030A CA3038A	
1	2	-16 V	0 V	4 10	6 13	-16 +12
2	3	-8 V	+1 V	1 3 4 10	2 4 6 13	0 0 -12 +12
3	4	-8 V	+1 V	1 2 4 10	2 3 6 13	0 0 -12 +12
-	5	NO CONNECTION				
4	6	-20 V	0 V	1 10	2 13	0 +12
-	7	NO CONNECTION				
5	8	DO NOT APPLY VOLTAGE FROM AN EXTERNAL SOURCE TO THIS TERMINAL				
6	9	DO NOT APPLY VOLTAGE FROM AN EXTERNAL SOURCE TO THIS TERMINAL				
7	10	0 V	+14 V	1 4 10	2 6 13	0 -12 +12
8	11	DO NOT APPLY VOLTAGE FROM AN EXTERNAL SOURCE TO THIS TERMINAL				
9	12	30 mA		4 10	6 13	-12 +12
				400 Ω Between Terminals 6 & 12 (CA3016A, CA3030A, CA3038A) 4 & 9 (CA3015A)		
10	13	0 V	+20 V	1 4	2 6	0 -12
11	14	0 V	+14 V	1 4 10	2 6 13	0 -12 +12
CASE	Internally connected to Terminal No.6, CA3016A, CA3030A, CA3038A No.4, CA3015A (Substrate) DO NOT GROUND					

CA3008A CA3010A
CA3016A CA3015A CA3029A
CA3037A CA3038A CA3030A

CA3016A CA3015A CA3008A CA:
CA3030A CA3038A CA3029A CA:

OPERATING TEMPERATURE RANGE . . . -55°C to $+125^\circ\text{C}$ 0°C to $+70^\circ\text{C}$
STORAGE TEMPERATURE RANGE . . . -65°C to $+200^\circ\text{C}$ -25°C to $+85^\circ\text{C}$

MAXIMUM SIGNAL VOLTAGE -8 V to +1 V -4 V to +1 V
MAXIMUM DEVICE DISSIPATION 600 mW 300 mW

Operational Amplifiers

CA3008A, CA3010A, CA3015A, CA3016A, CA3029A, CA3030A, CA3037A, CA3038A

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

Characteristics	Symbols	Special Test Conditions Terminal No.8 (CA3008A, CA3016A, CA3029A, CA3030A, CA3037A, CA3038A), Terminal No.5 (CA3010A, CA3015A) Not Connected Unless Otherwise Specified	Test Circuit	CA3008A CA3010A CA3029A CA3037A			CA3016A CA3015A CA3030A CA3038A			Units	Typical Characteristic Curves	
				Fig.	Min.	Typ.	Max.	Min.	Typ.			Max.
STATIC CHARACTERISTICS:												
Input Offset Voltage	V_{IO}	$V_{CC} = +6V, V_{EE} = -6V$ $= +12V = -12V$	4	-	0.9	2	-	-	-	mV	2	
Input Offset Current	I_{IO}	$= +6V = -6V$ $= +12V = -12V$	5	-	0.3	1.5	-	-	0.5 1.6	μA	2	
Input Bias Current	I_I	$= +6V = -6V$ $= +12V = -12V$	5	-	2.5	4	-	-	4.7 6	μA	3	
Input Offset Voltage Sensitivity:	Positive	$\Delta V_{IO}/\Delta V_{CC}$	4	-	0.10	1	-	-	0.096 0.5	mV/V	none	
	Negative	$\Delta V_{IO}/\Delta V_{EE}$		-	0.26	1	-	-	0.156 0.5			
Device Dissipation	P_T	$= +6V = -6V$ $= +12V = -12V$	4	-	40	-	-	-	-	mW	none	
		5 shorted to 9 8 shorted to 12		$V_{CC} = +6V, V_{EE} = -6V$ $V_{CC} = +12V, V_{EE} = -12V$	-	102	-	-	-			500
DYNAMIC CHARACTERISTICS: All tests at $f = 1\text{ kHz}$ except BW_{OL}												
Open-Loop Differential Voltage Gain	A_{OL}	$V_{CC} = +6V, V_{EE} = -6V$ $= +12V = -12V$	8	57	60	-	-	-	-	dB	6 & 7	
Open-Loop Bandwidth at -3 dB Point	BW_{OL}	$= +6V = -6V$ $= +12V = -12V$	8	200	300	-	-	-	-	kHz	6 & 7	
Slew Rate	SR	$V_{CC} = +6V, V_{EE} = -6V$ $= +12V = -12V$	$R_S = 1\text{ k}\Omega$	none	3	-	-	-	-	$\text{V}/\mu\text{s}$	none	
Common-Mode Rejection Ratio	CMR	$V_{CC} = +6V, V_{EE} = -6V$ $= +12V = -12V$	11	70	94	-	-	-	-	dB	12	
Maximum Output-Voltage Swing	$V_{O(P-P)}$	$= +6V = -6V$ $= +12V = -12V$	8	-	6.75	-	-	-	-	V_{P-P}	9 & 10	
Input Impedance	Z_{IN}	$= +6V = -6V$ $= +12V = -12V$	14	15	20	-	-	-	-	$\text{k}\Omega$	13	
Output Impedance	Z_{OUT}	$= +6V = -6V$ $= +12V = -12V$	15	-	160	-	-	-	-	Ω	16	
Common-Mode Input-Voltage Range	V_{CMR}	$= +6V = -6V$ $= +12V = -12V$	11	-	+0.5 -4	-	-	-	-	V	none	
Noise Figure	NF	$V_{CC} = +3V, V_{EE} = -3V$	$R_S = 1\text{ k}\Omega$	18	-	6.3	9	-	6.3	9	dB	17
		$= +6V = -6V$			-	8.3	12	-	8.3	12		
		$= +9V = -9V$			-	-	-	-	10	14		
		$= +12V = -12V$			-	-	-	-	11	16		

Linear Integrated Circuits

CA3008A, CA3010A, CA3015A, CA3016A, CA3029A, CA3030A, CA3037A, CA3038A

TYPICAL STATIC CHARACTERISTICS AND TEST CIRCUITS

Terminal Numbers in Circles are for CA3008A, CA3016A, CA3029A, CA3030A, CA3037A, CA3038A;
 Italic Numbers in Square Boxes are for CA3010A, CA3015A

INPUT OFFSET VOLTAGE AND CURRENT

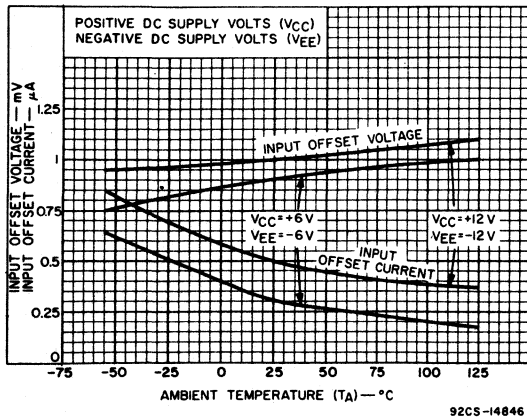


Fig.2

INPUT BIAS CURRENT

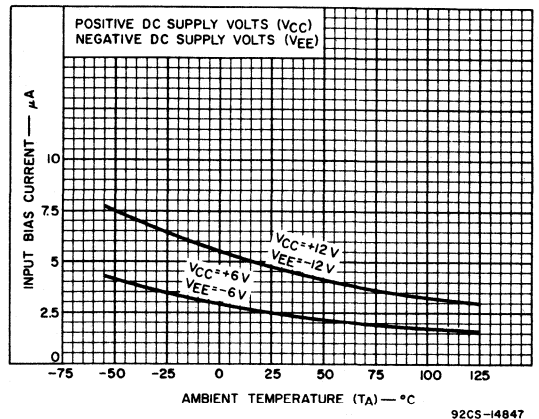


Fig.3

INPUT OFFSET VOLTAGE, INPUT OFFSET VOLTAGE SENSITIVITY, AND DEVICE DISSIPATION TEST CIRCUIT

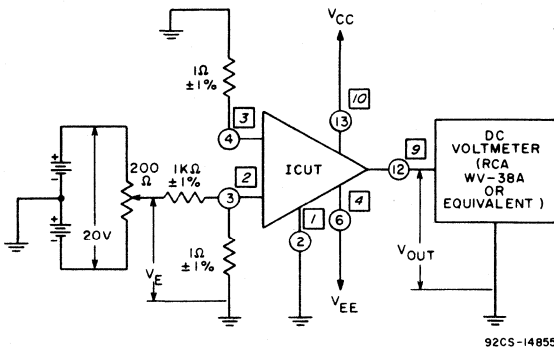


Fig.4

INPUT OFFSET CURRENT AND INPUT BIAS CURRENT TEST CIRCUIT

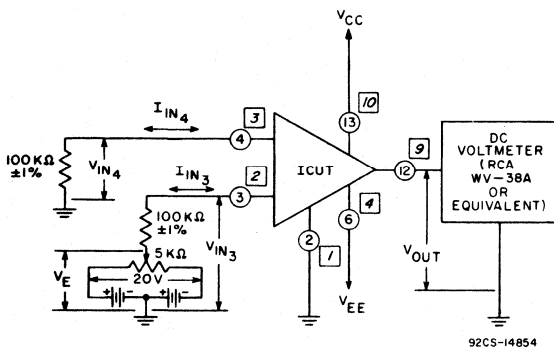


Fig.5

Procedure:

Input Offset Voltage

1. Adjust V_E for a DC Output Voltage (V_{OUT}) of 0 ± 0.1 volts.
2. Measure V_E and record Input Offset Voltage in millivolts as $V_E/1000$.

Input Offset Voltage Sensitivity

1. Adjust V_E for a DC Output Voltage (V_{OUT}) of 0 ± 0.1 volts.
2. Increase $|V_{CC}|$ by 1 volt and record output voltage (V_{OUT}).
3. Decrease $|V_{CC}|$ by 1 volt and record output voltage (V_{OUT}).
4. Divide the difference between V_{OUT} measured in steps 2 and 3 by the change in V_{CC} in steps 2 and 3.

$$\frac{V_{OUT}}{V_{CC}} = \frac{V_{OUT} (\text{Step 2}) - V_{OUT} (\text{Step 3})}{2 \text{ volts}}$$

5. Refer the reading to the input by dividing by Open Loop Voltage Gain (A_{OL}).

$$V_{IO}/V_{CC} = \frac{V_{OUT}/V_{CC}}{A_{OL}}$$

6. Repeat procedures 1 through 5 for the Negative Supply (V_{EE}).

7. Device Dissipation

$$P_T = V_{CC}I_C + V_{EE}I_E$$

I_C = Direct Current into Terminal 13 or $\textcircled{10}$

I_E = Direct Current out of Terminal 6 or $\textcircled{4}$

Procedure:

Input Bias Current and Input Offset Current

1. Adjust V_E for $|V_{OUT}| < 0.1$ V DC.
2. Measure and record V_E and V_{IN4}
3. Calculate the Input Bias Current using the following equation:

$$I_{I4} = \frac{V_{IN4}}{100 \text{ k}\Omega}$$

4. Calculate the Input Offset Current using the following equation:

$$I_{IO} = V_E/100 \text{ k}\Omega$$

CA3008A, CA3010A, CA3015A, CA3016A, CA3029A, CA3030A, CA3037A, CA3038A

TYPICAL DYNAMIC CHARACTERISTICS AND TEST CIRCUITS

Terminal Numbers in Circles are for CA3008A, CA3016A, CA3029A, CA3030A, CA3037A, CA3038A;
 Italic Numbers in Square Boxes are for CA3010A, CA3015A

OPEN LOOP VOLTAGE GAIN vs. FREQUENCY
 FOR CA3008A, CA3010A, CA3015A, CA3016A,
 CA3037A, CA3038A

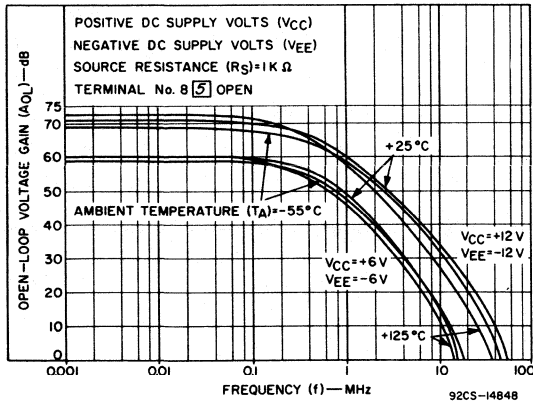


Fig. 6

OPEN LOOP VOLTAGE GAIN vs. FREQUENCY
 FOR CA3029A AND CA3030A.

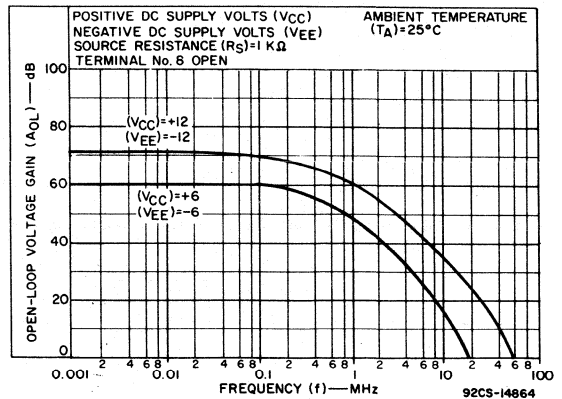
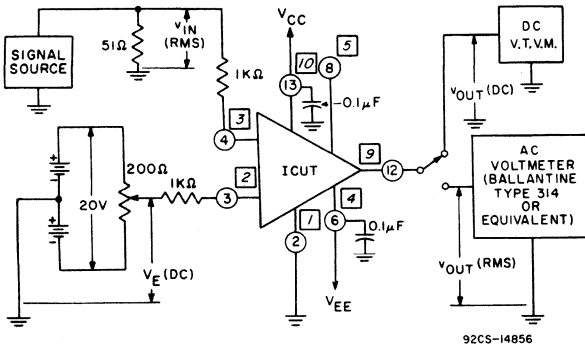


Fig. 7

OPEN-LOOP DIFFERENTIAL VOLTAGE GAIN, MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE, AND OPEN-LOOP BANDWIDTH AT -3 POINT TEST CIRCUIT



92CS-14856

Procedure:

1. Adjust V_E for $V_{OUT} = \pm 0.1$ V DC.
2. Measure Open-Loop Differential Voltage Gain (A_{OL}) at $f = 1$ kHz

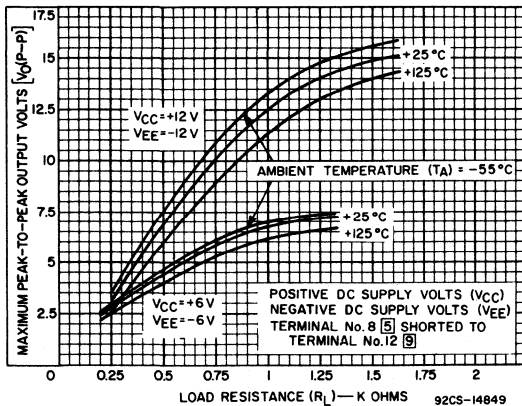
$$A_{OL} = 20 \log_{10} \frac{V_{OUT}}{V_{IN}}$$

3. Measure Maximum Peak-to-Peak Output Voltage at $f = 1$ kHz
4. Measure Open-Loop Bandwidth at -3 dB Point

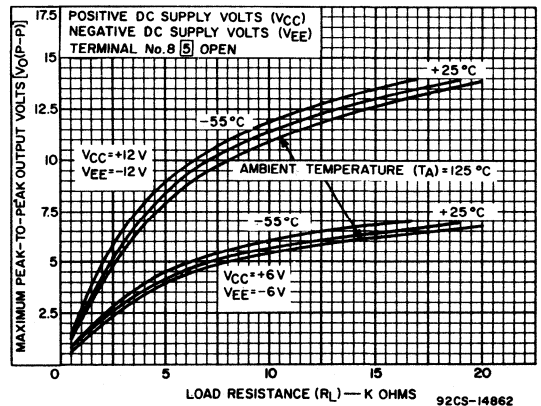
Reference Level = A_{OL} at 1 kHz

Fig. 8

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE vs. LOAD RESISTANCE
 FOR CA3008A, CA3010A, CA3015A, CA3016A, CA3037A, CA3038A



(a)



(b)

Fig. 9

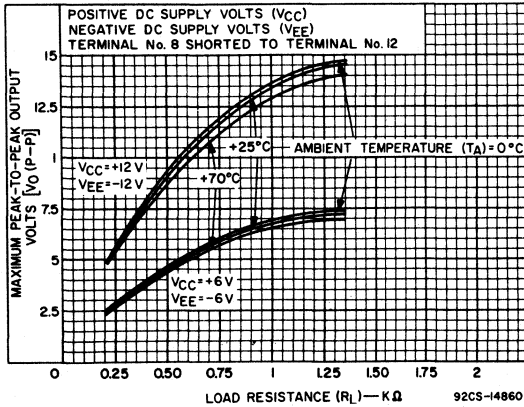
Linear Integrated Circuits

CA3008A, CA3010A, CA3015A, CA3016A, CA3029A, CA3030A, CA3037A, CA3038A

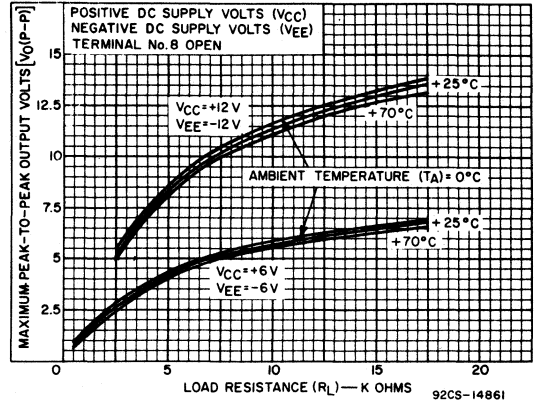
TYPICAL DYNAMIC CHARACTERISTICS AND TEST CIRCUITS

Terminal Numbers in Circles are for CA3008A, CA3016A, CA3029A, CA3030A, CA3037A, CA3038A;
 Italic Numbers in Square Boxes are for CA3010A, CA3015A

MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE vs. LOAD RESISTANCE FOR CA3029A AND CA3030A



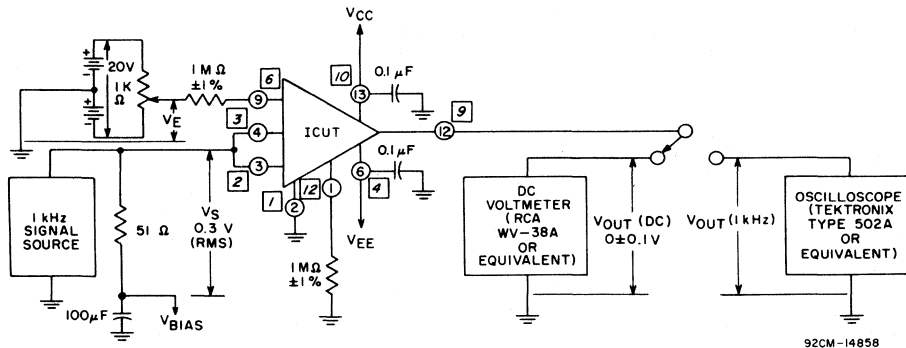
(a)



(b)

Fig.10

COMMON-MODE REJECTION RATIO AND COMMON-MODE INPUT-VOLTAGE-RANGE TEST CIRCUIT



92CM-14858

Procedures:

Common-Mode Rejection Ratio:

1. Set $V_{BIAS} = 0$. Adjust V_E for $V_{OUT}(DC) = 0 \pm 0.1$ V.
2. Apply 1-kHz sinusoidal input signal and adjust for $V_S = 0.3$ V (RMS).
3. Measure and record the RMS value of V_{OUT} . An oscilloscope is used for this measurement so that the output signal may be visually separated from noise output.
4. Calculate Common-Mode Voltage Gain:

$$A_{CM} = V_{OUT}/V_S$$

$$A_{CM} \text{ in dB} = -20 \text{ LOG}_{10} V_S/V_{OUT}$$

5. Calculate Common-Mode Rejection Ratio:

$$\text{CMR in dB} = A_{DIFF} \text{ in dB} - A_{CM} \text{ in dB.}$$

Common-Mode Input-Voltage Range:

1. Calculate and record CMR for various positive and negative values of V_{BIAS} within the maximum limits shown on Page 2. The Common-Mode Input-Voltage Range limits are those values of V_{BIAS} at which CMR is 6 dB less than that calculated in Step 5 of the procedure given above.

Fig.11

COMMON-MODE REJECTION RATIO vs. FREQUENCY

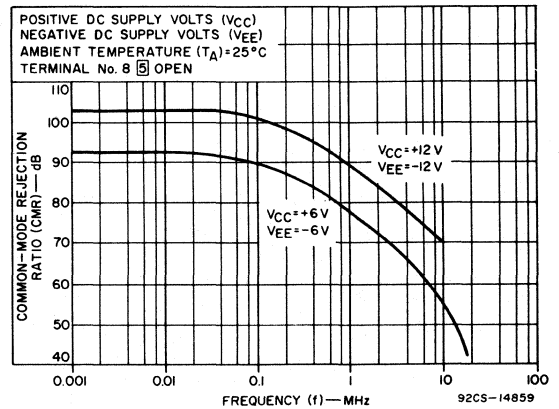


Fig.12

92CS-14859

CA3008A, CA3010A, CA3015A, CA3016A, CA3029A, CA3030A, CA3037A, CA3038A

TYPICAL DYNAMIC CHARACTERISTICS AND TEST CIRCUITS

Terminal Numbers in Circles are for CA3008A, CA3016A, CA3029A, CA3030A, CA3037A, CA3038A;
Italic Numbers in Square Boxes are for CA3010A, CA3015A

SINGLE-ENDED INPUT IMPEDANCE vs. TEMPERATURE

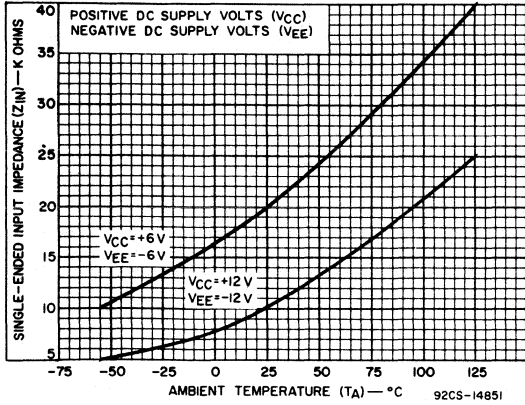


Fig. 13

SINGLE-ENDED INPUT IMPEDANCE TEST CIRCUIT

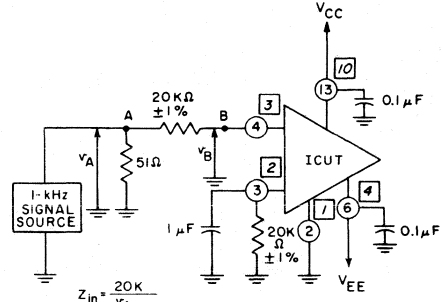


Fig. 14

OUTPUT IMPEDANCE TEST CIRCUIT

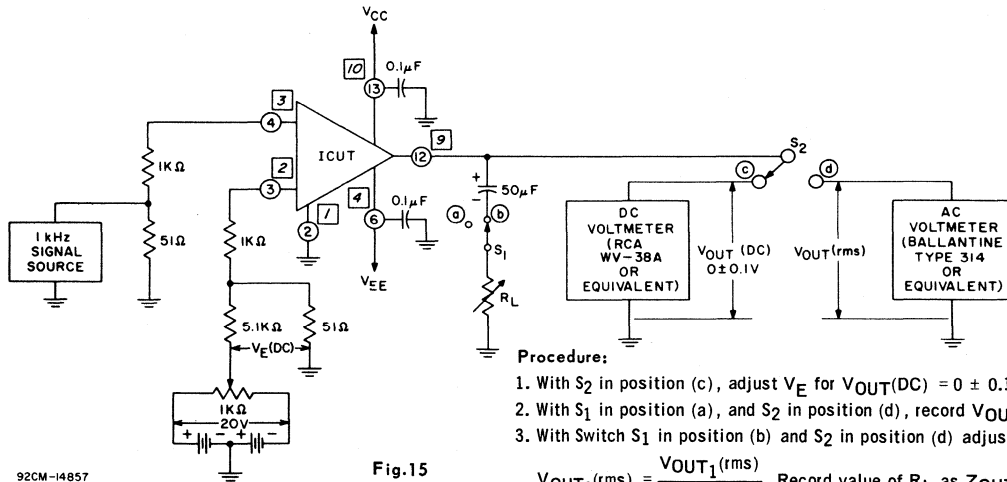
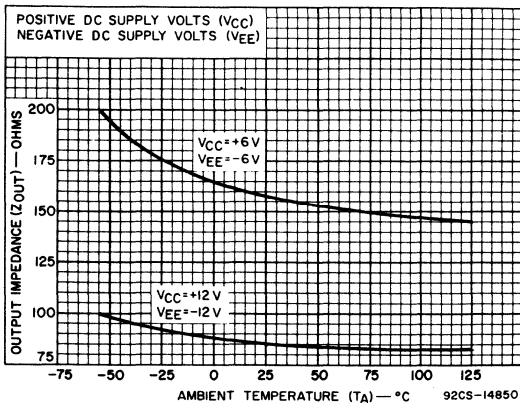


Fig. 15

Procedure:

1. With S_2 in position (c), adjust V_E for $V_{OUT}(DC) = 0 \pm 0.1$ V.
2. With S_1 in position (a), and S_2 in position (d), record $V_{OUT1}(rms)$.
3. With Switch S_1 in position (b) and S_2 in position (d) adjust R_L until

$$V_{OUT2}(rms) = \frac{V_{OUT1}(rms)}{2}. \text{ Record value of } R_L \text{ as } Z_{OUT}.$$



OUTPUT IMPEDANCE vs. TEMPERATURE

Fig. 16

Linear Integrated Circuits

CA3008A, CA3010A, CA3015A, CA3016A, CA3029A, CA3030A, CA3037A, CA3038A

NOISE FIGURE vs. FREQUENCY

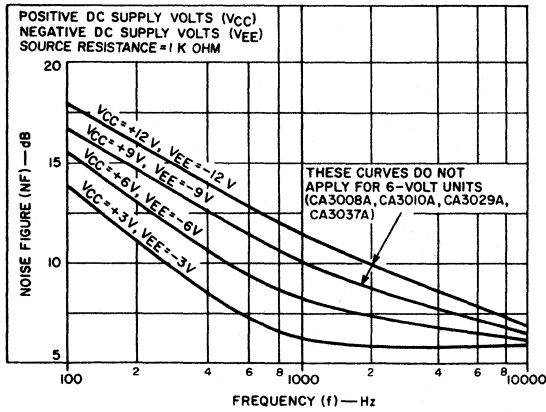


Fig. 17

NOISE FIGURE TEST CIRCUIT

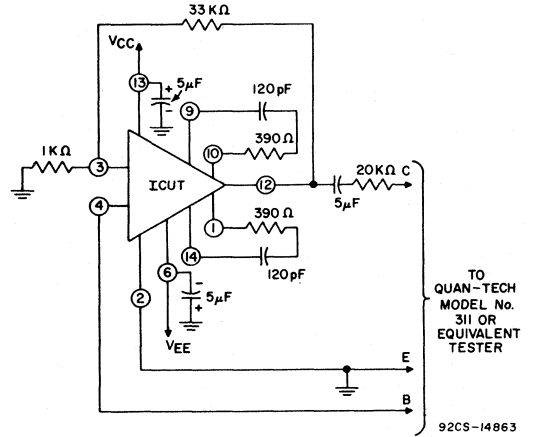
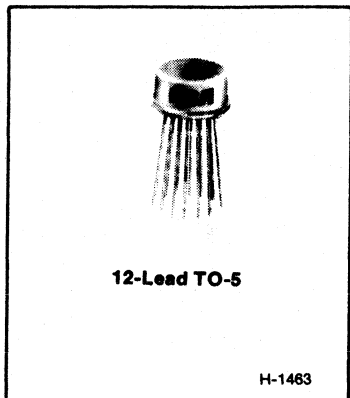


Fig. 18

Low-Power Wideband Amplifiers



Features:

- **Lower DC Power Drain:**

{	CA3021 = 4 mW typ.	}	at $V_{CC} = 6\text{ V}$
	CA3022 = 12.5 mW typ.		
	CA3023 = 35 mW typ.		
- **Excellent frequency response:**

-3dB BW	CA3021 = 2.4 MHz typ.	}
	CA3022 = 7.5 MHz typ.	
	CA3023 = 16 MHz typ.	
- **High Voltage Gain:**

A	CA3021 = 56 dB typ. at 0.5 MHz	}
	CA3022 = 57 dB typ. at 2.5 MHz	
	CA3023 = 53 dB typ. at 5 MHz	
- **Wide AGC Range:** 33 dB typ.
- **Only one power supply** (4.5 to 12 V) required
- **Hermetically sealed 12-lead TO-5-style package**
- **Operation from -55°C to $+125^{\circ}\text{C}$**

Applications:

- Gain-controlled linear amplifiers
- AM/FM IF amplifiers
- Video amplifiers
- Limiters

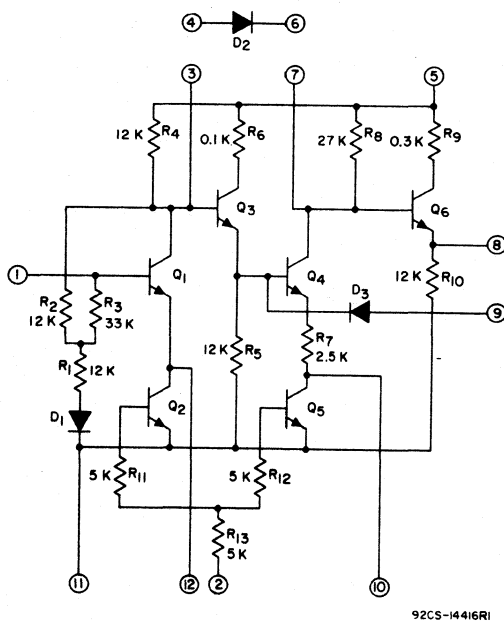


Fig. 1 - Schematic diagram for CA3021, CA3022, and CA3023.

Linear Integrated Circuits

CA3021, CA3022, CA3023

ABSOLUTE-MAXIMUM RATINGS:

OPERATING-TEMPERATURE RANGE	-55°C to +125°C	
STORAGE-TEMPERATURE RANGE	-65°C to +150°C	
LEAD TEMPERATURE (During Soldering):		
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm)		
from case for 10 seconds max.	+265°C	
DEVICE DISSIPATION, P _T	120 max.	mW
INPUT-SIGNAL VOLTAGE	-3, +3 max.	V
DC VOLTAGES AND CURRENTS	See Table Below	

TERMINAL	VOLTAGE OR CURRENT LIMITS		CIRCUIT CONDITIONS	
	NEGATIVE	POSITIVE	TERMINAL	CONDITIONS
1	-3V	+3V	1	Connected to Voltage Source through 100Ω Resistor
			5	+12V
			10, 11, 12	Ground
2	-3V	+12V	5	+12V
			10, 11, 12	Ground
3	0V	+12V	5	+12V
			10, 11, 12	Ground
4	-12V 10 max. mA	+12V	6, 11	Ground
5	0V	+18V	10, 11, 12	Ground
6	-12V 10 max. mA	+12V	5, 11	Ground

TERMINAL	VOLTAGE OR CURRENT LIMITS		CIRCUIT CONDITIONS	
	NEGATIVE	POSITIVE	TERMINAL	CONDITIONS
7	0V	+12V	5	+12V
			10, 11, 12	Ground
8	20 max. mA		5	+12V
			10, 11, 12	Ground
9	-0.5V	+3V	5	+12V
			10, 11, 12	Ground
10	0V	+4V	2,5	+12V
			11	Ground
11	-6V	+12V	2	Ground
			5	+12V
12	0V	+4V	2,5	+12V
			11	Ground

CA3021, CA3022, CA3023

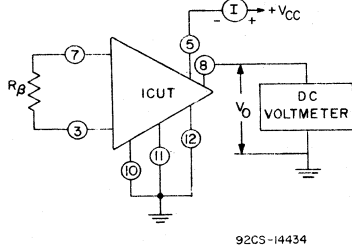
ELECTRICAL CHARACTERISTICS, at $T_A = 25^\circ\text{C}$, $V_{CC} = +6\text{V}$, unless otherwise specified

CHARACTERISTIC	SYMBOL	TEST CONDITIONS				LIMITS									TYPICAL CHARACTERISTIC CURVE
		TEST SETUP AND PROCEDURE	FEEDBACK RESISTANCE (R_{β}) BETWEEN TERMINALS 3 AND 7	FREQUENCY f	CA3021 (TA5219)			CA3022 (TA5236)			CA3023 (TA5218)			UNITS	
					Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.		
Device Dissipation	P_T	2	∞	-	1	4	8	-	-	-	-	-	-	mW	3a,d
			∞	-	-	-	-	5	12.5	24	-	-	-	mW	3b,d
			∞	-	-	-	-	-	-	-	24	35	48	mW	3c,d
Quiescent Output Voltage	V_o	2	39k	-	-	2.2	-	-	-	-	-	-	V	-	
			10k	-	-	-	-	1.9	-	-	-	-	V		
			4.7k	-	-	-	-	-	-	-	1.3	-	V		
AGC Source Current	I_{AGC}	4	$V_{AGC} = +6\text{V}$		-	0.8	-	-	0.8	-	-	0.8	-	mA	-
Voltage Gain	A	5	560k	0.5	50	56	-	-	-	-	-	-	-	dB	6a
			39k	0.8	40	46	-	-	-	-	-	-	-	dB	6a,d
			39k	2.5	-	-	-	50	57	-	-	-	-	dB	6b
			10k	3	-	-	-	40	44	-	-	-	-	dB	6b,d
			18k	5	-	-	-	-	-	-	50	53	-	dB	6c
			4.7k	10	-	-	-	-	-	-	40	44	-	dB	6c,d
Bandwidth at -3 dB Point	BW	5	39k	-	0.8	2.4	-	-	-	-	-	-	-	MHz	6a
			10k	-	-	-	-	3	7.5	-	-	-	-	MHz	6b
			4.7k	-	-	-	-	-	-	-	10	16	-	MHz	6c
Input-Impedance Components	Input Resistance	R_{IN}	7	39k	1	-	4000	-	-	-	-	-	-	Ω	-
				10k	5	-	-	-	-	1300	-	-	-	Ω	
				4.7k	10	-	-	-	-	-	-	300	-	Ω	
	Input Capacitance	C_{IN}	7	39k	1	-	11	-	-	-	-	-	-	pF	-
				10k	5	-	-	-	-	18	-	-	-	pF	
				4.7k	10	-	-	-	-	-	-	13	-	pF	
Output Resistance	R_{OUT}	8	39k	1	-	300	-	-	-	-	-	-	Ω	-	
			10k	5	-	-	-	-	120	-	-	-	Ω		
			4.7k	10	-	-	-	-	-	-	100	-	Ω		
Noise Figure	NF	9	39k	1	-	4.2	8.5	-	-	-	-	-	dB	-	
			10k	1	-	-	-	-	4.4	8.5	-	-	dB		
			4.7k	1	-	-	-	-	-	-	-	6.5	8.5		dB
AGC Range	AGC	10	-	1	-	33	-	-	-	-	-	-	dB	-	
			-	5	-	-	-	-	33	-	-	-	dB		
			-	10	-	-	-	-	-	-	-	33	-		dB
Maximum Output Voltage (RMS Value)	V_{out}	5	39k	1	-	0.6	-	-	-	-	-	-	$V_{(rms)}$	-	
			10k	5	-	-	-	-	0.7	-	-	-	$V_{(rms)}$		
			4.7k	10	-	-	-	-	-	-	-	0.5	$V_{(rms)}$		

Linear Integrated Circuits

CA3021, CA3022, CA3023

TEST SETUP FOR MEASUREMENT OF DEVICE DISSIPATION AND QUIESCENT OUTPUT VOLTAGE



$$P_T = V_{CC} (I)$$

Fig. 2

DEVICE DISSIPATION VS DC SUPPLY VOLTAGE FOR CA3022

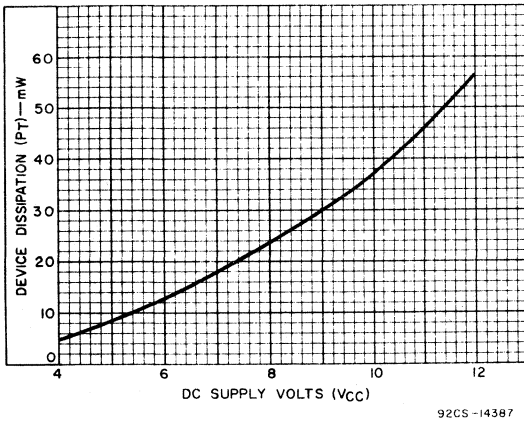


Fig. 3(b)

DEVICE DISSIPATION VS DC SUPPLY VOLTAGE FOR CA3021

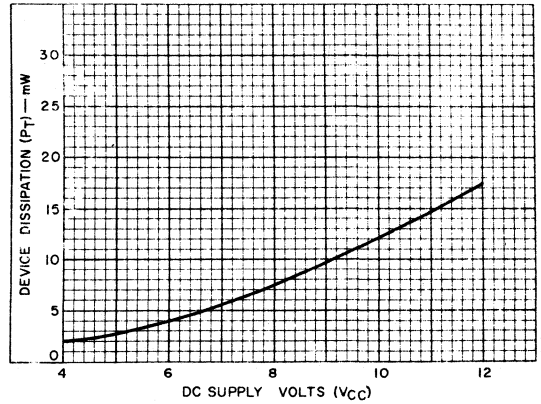


Fig. 3(a)

DEVICE DISSIPATION VS DC SUPPLY VOLTAGE FOR CA3023

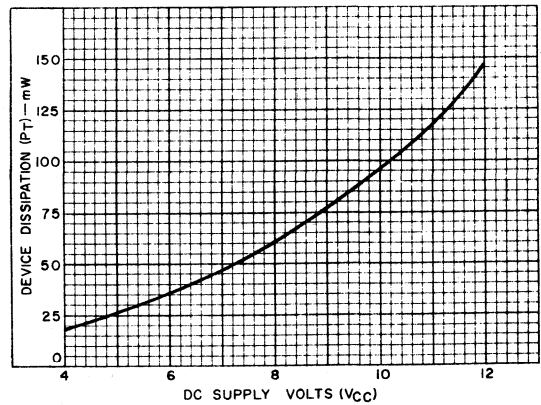


Fig. 3(c)

DEVICE DISSIPATION VS TEMPERATURE FOR CA3021, CA3022, AND CA3023

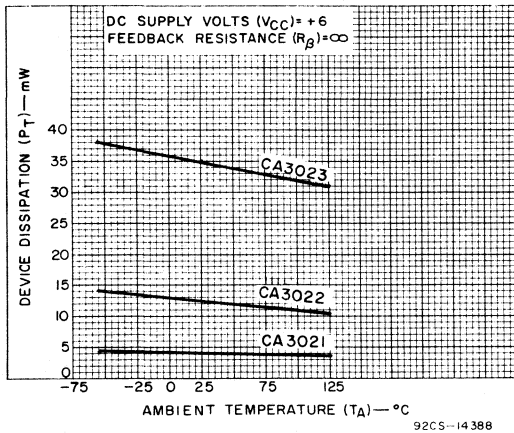
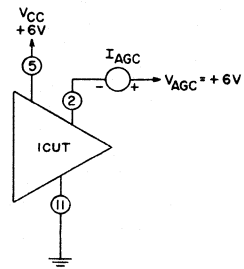


Fig. 3(d)

TEST SETUP FOR MEASUREMENT OF AGC SOURCE CURRENT

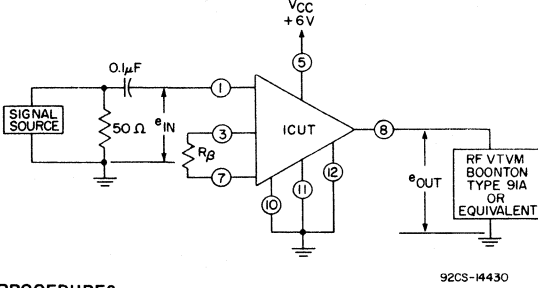


I_{AGC} IS THE CURRENT FLOWING INTO TERMINAL 2.

Fig. 4

CA3021, CA3022, CA3023

TEST SETUP FOR MEASUREMENTS OF VOLTAGE-GAIN, -3dB BANDWIDTH, AND MAXIMUM OUTPUT VOLTAGE



PROCEDURES

Voltage Gain:

(a) Set $e_{in} = 0.5 \text{ mV}$ at frequency specified, read e_{out} Voltage Gain

$$(A) = 20 \text{ Log}_{10} \frac{e_{out}}{e_{in}}$$

Bandwidth:

(a) Set e_{out} to a convenient reference voltage at $f = 100 \text{ kHz}$ and record corresponding value of e_{in} .

(b) Increase the frequency, keeping e_{in} constant until e_{out} drops 3-dB. Record Bandwidth.

Fig. 5

VOLTAGE GAIN VS FREQUENCY FOR CA3021

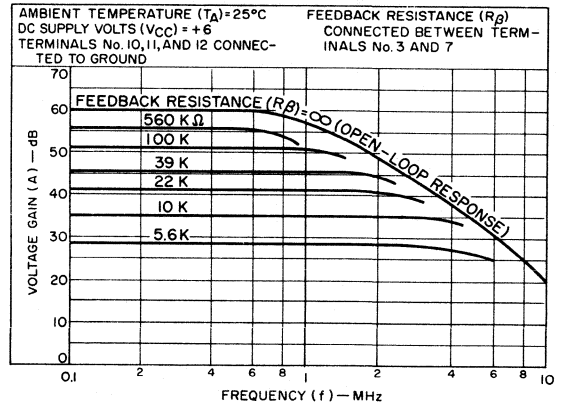


Fig. 6(a)

VOLTAGE GAIN VS FREQUENCY FOR CA3022

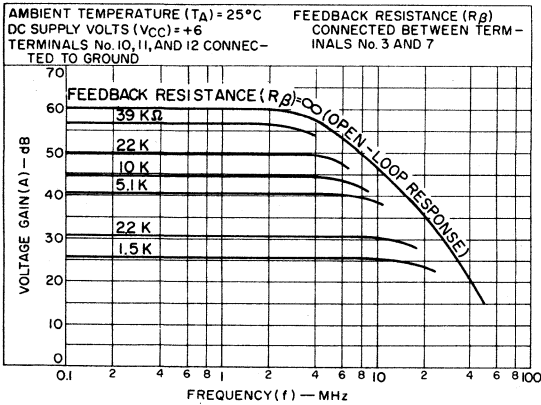


Fig. 6(b)

VOLTAGE GAIN VS FREQUENCY FOR CA3023

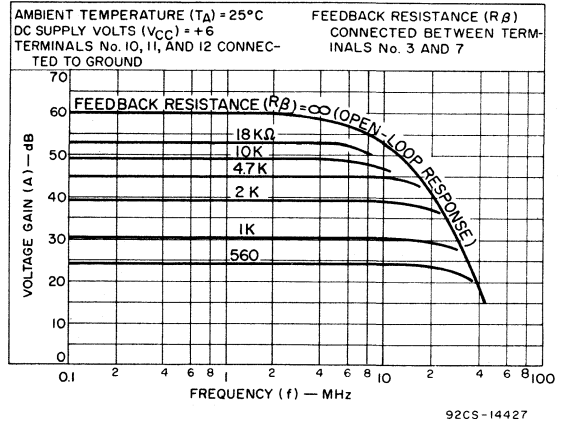


Fig. 6(c)

DC SUPPLY VOLTS (V_{CC}) = +6 TERMINALS No. 10, 11, AND 12 CONNECTED TO GROUND FEEDBACK RESISTANCE (R_β) CONNECTED BETWEEN TERMINALS No. 3 AND No. 7	TYPE	R_β	f
		K Ω	MHz
	CA3021	39	1
	CA3022	10	5
	CA3023	4.7	10

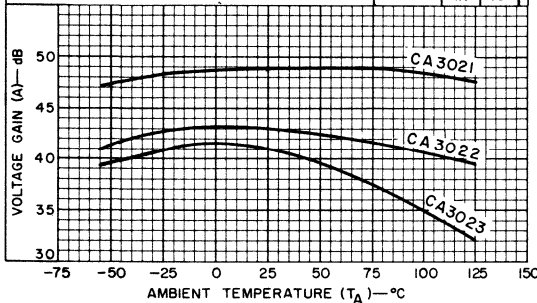


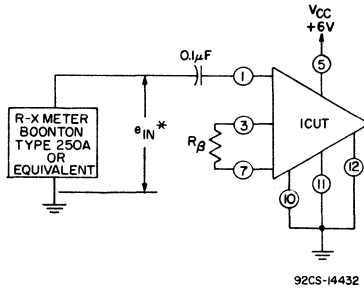
Fig. 6(d)

VOLTAGE GAIN VS TEMPERATURE FOR CA3021, CA3022, AND CA3023

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CA3021, CA3022, CA3023

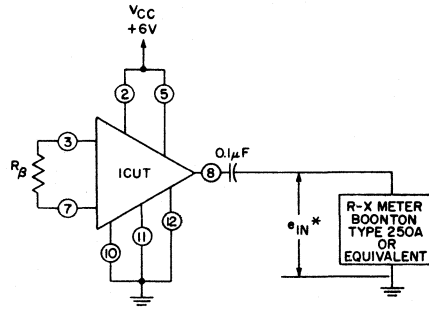
TEST SETUP FOR MEASUREMENT OF INPUT-IMPEDANCE COMPONENTS



* $e_{in} \leq 10 \text{ mV}$

Fig.7

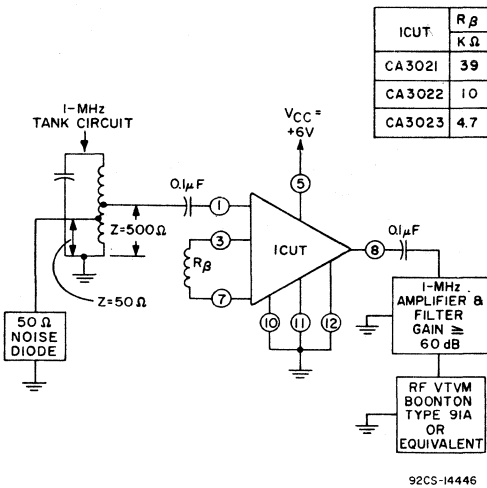
TEST SETUP FOR MEASUREMENT OF OUTPUT RESISTANCE



* $e_{in} \leq 10 \text{ mV}$

Fig.8

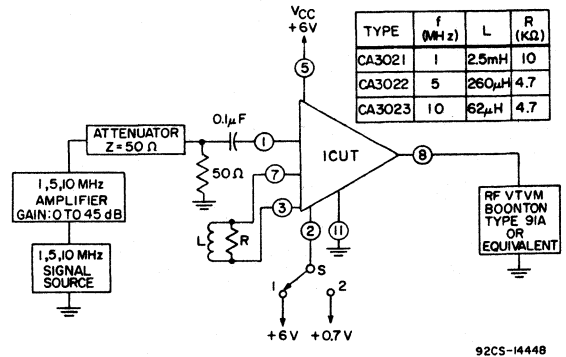
TEST SETUP FOR MEASUREMENT OF NOISE FIGURE



CA3021 - $R_{\beta} = 39 \text{ k}\Omega$
 CA3022 - $R_{\beta} = 10 \text{ k}\Omega$
 CA3023 - $R_{\beta} = 4.7 \text{ k}\Omega$

Fig.9

TEST SETUP FOR MEASUREMENT OF AGC RANGE



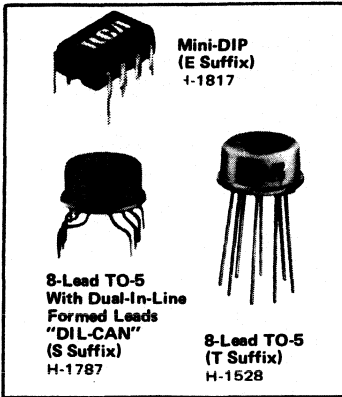
$$\text{AGC RANGE} = 20 \text{ LOG}_{10} \frac{\text{A WITH S IN POSITION 1}}{\text{A WITH S IN POSITION 2}}$$

(A = VOLTAGE GAIN)

	f
	MHz
CA3021	1
CA3022	5
CA3023	10

Fig.10

Wideband Operational Amplifier



Features:

- High open-loop gain at video frequencies - 42 dB typ. at 1 MHz
- High unity-gain crossover frequency (f_T) - 38 MHz typ.
- Wide power bandwidth - $V_o = 18$ Vp-p typ. at 1.2 MHz
- High slew rate - 70 V/ μ s [typ.] in 20 dB amplifier
25 V/ μ s [typ.] in unity-gain amplifier
- Fast settling time - 0.6 μ s typ.
- High output current - ± 15 mA min.
- LM118, 748/LM101 pin compatibility

- Single capacitor compensation
- Offset null terminals

Applications:

- Video amplifiers
- Fast peak detectors
- Meter-driver amplifiers
- High-frequency feedback amplifiers
- Video pre-drivers
- Oscillators
- Multivibrators
- Voltage-controlled oscillator
- Fast comparators

RCA-CA3100S, CA3100T is a large-signal wideband, high-speed operational amplifier which has a unity gain crossover frequency (f_T) of approximately 38 MHz and an open-loop, 3 dB corner frequency of approximately 110 kHz. It can operate at a total supply voltage of from 14 to 36 volts (± 7 to ± 18 volts when using split supplies) and can provide at least 18 Vp-p and 30 mA p-p at the output when operating from ± 15 volt supplies. The CA3100 can be compensated with a single external capacitor and has dc offset adjust

terminals for those applications requiring offset null. (See Fig. 15).

The CA3100 circuit contains both bipolar and P-MOS transistors on a single monolithic chip.

The CA3100 is supplied in either the standard 8-lead TO-5 package ("T" suffix), or in the 8-lead TO-5 dual-in-line formed-lead "DIL-CAN" package ("S" suffix).

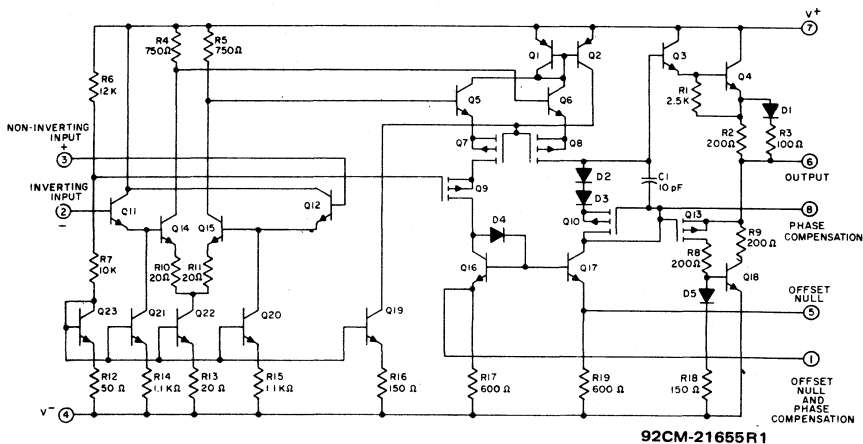


Fig. 1 — Schematic diagram for CA3100.

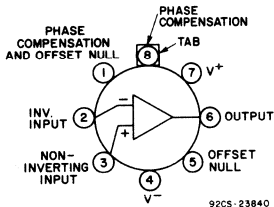
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CA3100 Types

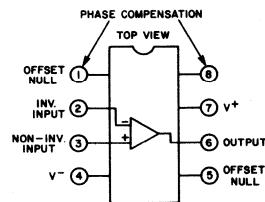
ELECTRICAL CHARACTERISTICS, At $T_A = 25^\circ\text{C}$:

CHARACTERISTICS	TEST CONDITIONS SUPPLY VOLTAGE (V^+, V^-) = 15 V UNLESS OTHERWISE SPECIFIED	LIMITS			UNITS
		MIN.	TYP.	MAX.	
STATIC					
Input Offset Voltage, V_{IO}	$V_O = 0 \pm 0.1 \text{ V}$	—	± 1	± 5	mV
Input Bias Current, I_{IB}	$V_O = 0 \pm 1 \text{ V}$	—	0.7	2	μA
Input Offset Current, I_{IO}		—	± 0.05	± 0.4	μA
Low-Frequency Open-Loop Voltage Gain, A_{OL}^*	$V_O = \pm 1 \text{ V Peak, } F = 1 \text{ kHz}$	56	61	—	dB
Common-Mode Input Voltage Range, V_{ICR}	$\text{CMRR} \geq 76 \text{ dB}$	± 12	+14 -13	—	V
Common-Mode Rejection Ratio, CMRR	$V_I \text{ Common Mode} = \pm 12 \text{ V}$	76	90	—	dB
Maximum Output Voltage: Positive, V_{OM}^+	Differential Input Voltage = $0 \pm 0.1 \text{ V}$ $R_L = 2 \text{ K}\Omega$	+9	+11	—	V
Negative, V_{OM}^-		-9	-11	—	
Maximum Output Current: Positive, I_{OM}^+	Differential Input Voltage = $0 \pm 0.1 \text{ V}$ $R_L = 250 \Omega$	+15	+30	—	mA
Negative, I_{OM}^-		-15	-30	—	
Supply Current, I^+	$V_O = 0 \pm 0.1 \text{ V, } R_L \geq 10 \text{ K}\Omega$	—	8.5	10.5	mA
Power-Supply Rejection Ratio, PSRR	$\Delta V^+ = \pm 1 \text{ V, } \Delta V^- = \pm 1 \text{ V}$	60	70	—	dB
DYNAMIC					
Unity-Gain Crossover Frequency, f_T	$C_C = 0, V_O = 0.3 \text{ V (P-P)}$	—	38	—	MHz
1-MHz Open-Loop Voltage Gain, A_{OL}	$f = 1 \text{ MHz, } C_C = 0, V_O = 10 \text{ V (P-P)}$	36	42	—	dB
Slew Rate, SR: 20-dB Amplifier	$A_V = 10, C_C = 0, V_I = 1 \text{ V (Pulse)}$	50	70	—	V/ μs
	Follower Mode $A_V = 1, C_C = 10 \text{ pF, } V_I = 10 \text{ V (Pulse)}$	—	25	—	
Power Bandwidth, PBW [▲] : 20-dB Amplifier	$A_V = 10, C_C = 0, V_O = 18 \text{ V (P-P)}$	0.8	1.2	—	MHz
	Follower Mode $A_V = 1, C_C = 10 \text{ pF, } V_O = 18 \text{ V (P-P)}$	—	0.4	—	
Open-Loop Differential Input Impedance, Z_I	$F = 1 \text{ MHz}$	—	30	—	$\text{K}\Omega$
Open-Loop Output Impedance, Z_O	$F = 1 \text{ MHz}$	—	110	—	Ω
Wideband Noise Voltage Referred to Input, $e_N(\text{Total})$	$\text{BW} = 1 \text{ MHz, } R_S = 1 \text{ K}\Omega$	—	8	—	μV_{RMS}
Settling Time, t_s [To Within $\pm 50 \text{ mV}$ of 9 V Output Swing]	$R_L = 2 \text{ K}\Omega, C_L = 20 \text{ pF}$	—	0.6	—	μs

▲ Power Bandwidth = $\frac{\text{Slew Rate}}{\pi V_O \text{ (P-P)}}$ • Low-frequency dynamic characteristic



S & T Suffixes



E Suffix

TERMINAL ASSIGNMENTS

MAXIMUM RATINGS, Absolute-Maximum Values:

Supply Voltage (between V+ and V- terminals)	36	V
Differential Input Voltage	±12	V
Input Voltage to Ground*	±15	V
Offset Terminal to V- Terminal Voltage	±0.5	V
Output Current	50	mA
Device Dissipation:		
Up to T _A = 55°C	630	mW
Above T _A = 55°C	6.67	mW/°C
Ambient Temperature Range:		
Operating:		
E Type	-40 to +85	°C
S and T Types	-55 to +125	°C
Storage	-65 to +150	°C
Lead Temperature (During Soldering):		
At distance 1/16 ± 1/32 inch (1.59 ± 0.79 mm) from case for 10 s max.	+265	°C

- * If the supply voltage is less than ±15 volts, the maximum input voltage to ground is equal to the supply voltage.
- CA3100S, CA3100T does not contain circuitry to protect against short circuits in the output.

TYPICAL CHARACTERISTIC CURVES

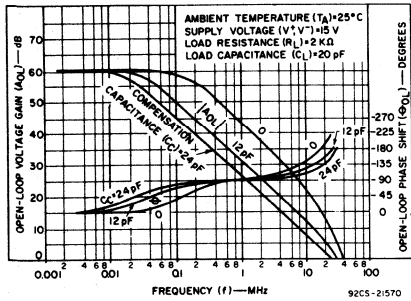


Fig. 2 - Open-loop gain, open-loop phase shift vs. frequency.

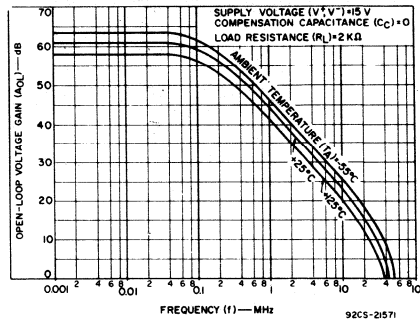


Fig. 3 - Open-loop gain vs. frequency and temperature.

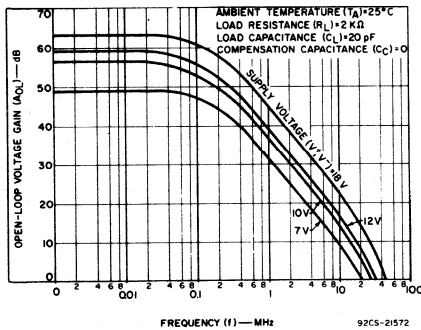


Fig. 4 - Open-loop gain vs. frequency and supply voltage.

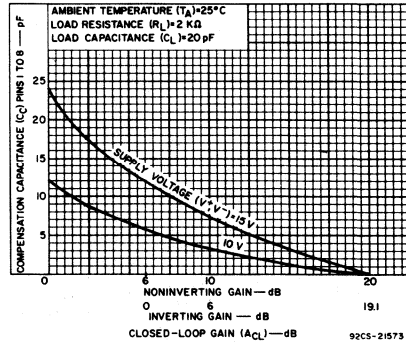


Fig. 5 - Required compensation capacitance vs. closed-loop gain.

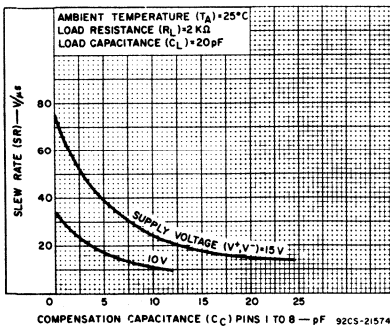


Fig. 6 - Slew rate vs. compensation capacitance.

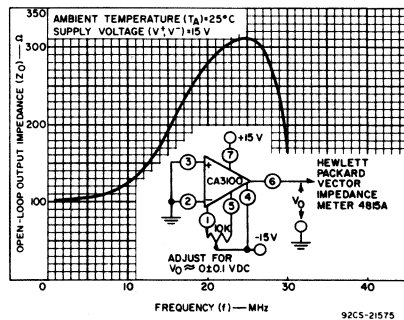


Fig. 7 - Typical open-loop output impedance vs. frequency.

Linear Integrated Circuits

CA3100 Types

TYPICAL CHARACTERISTIC CURVES (Cont'd)

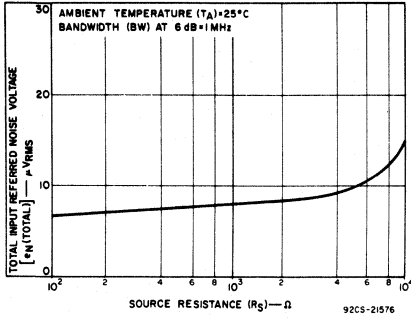


Fig. 8 - Wideband input noise voltage vs. source resistance.

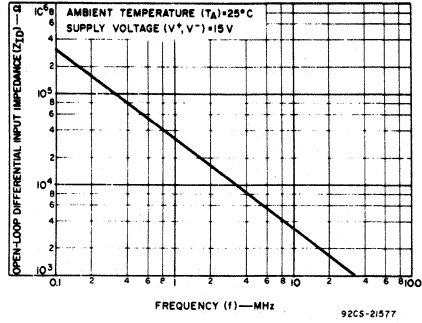


Fig. 9 - Typical open-loop differential input impedance vs. frequency.

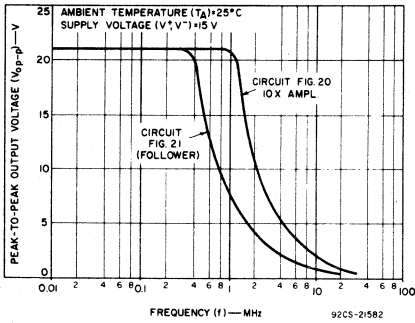


Fig. 10 - Maximum output voltage swing vs. frequency.

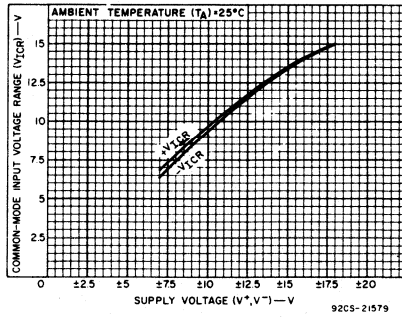


Fig. 11 - Common-mode input voltage range vs. supply voltage.

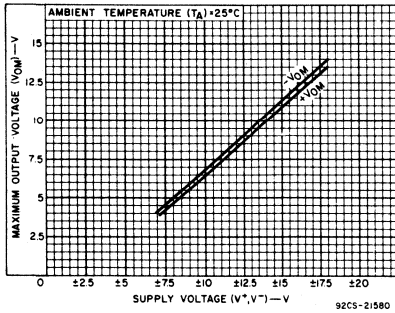


Fig. 12 - Maximum output voltage vs. supply voltage.

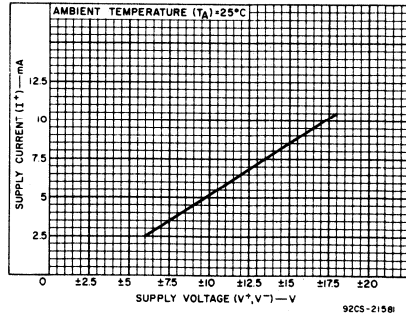


Fig. 13 - Supply current vs. supply voltage.

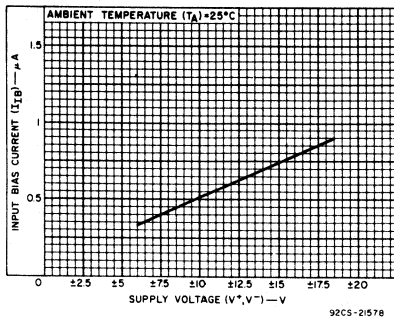
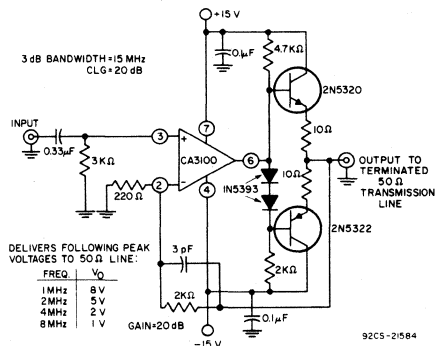
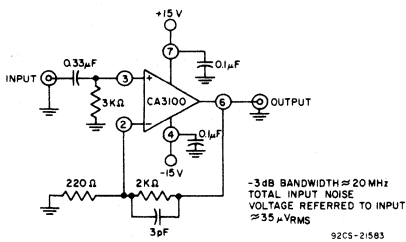
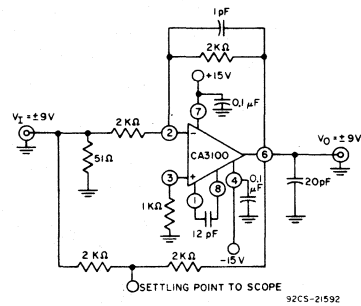
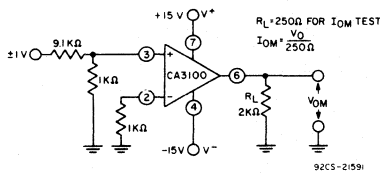
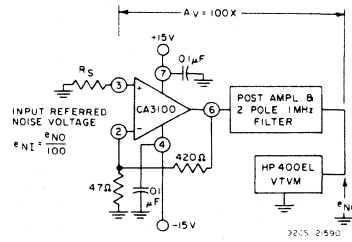
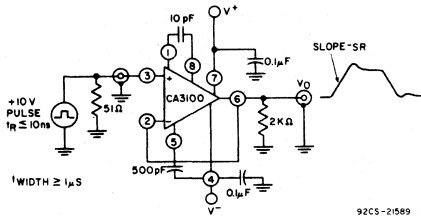
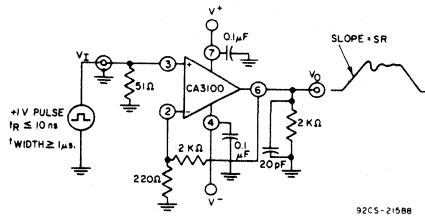
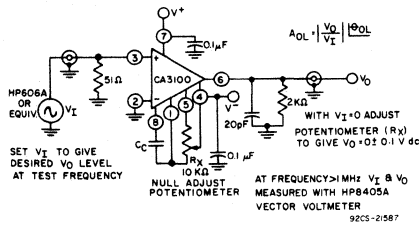


Fig. 14 - Input bias current vs. supply voltage.

TEST CIRCUITS



TYPICAL APPLICATIONS

Fig. 21 - 20 dB video amplifier.

Fig. 22 - 20 dB video line driver.

CA3100 Types

TYPICAL APPLICATIONS (Cont'd)

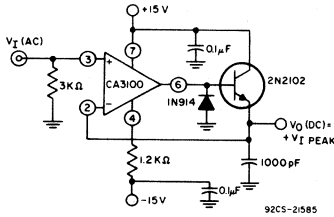


Fig. 23 - Fast positive peak detector.

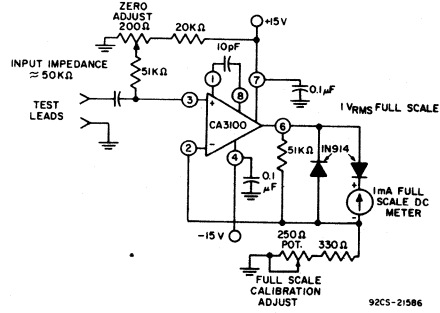
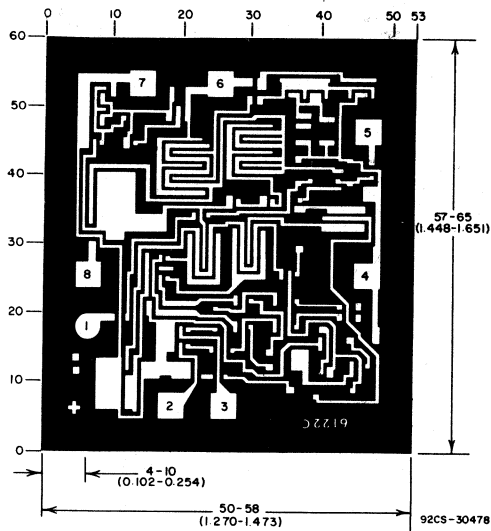


Fig. 24 - 1 MHz meter-driver amplifier.

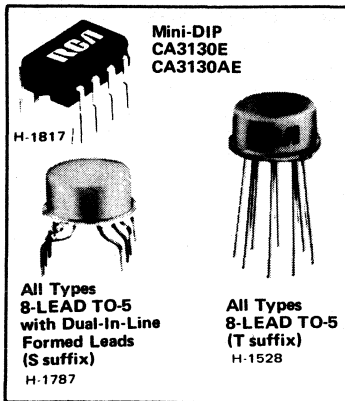
Chip Dimensions and Pad Layout



CA3100H Chip

The photographs and dimensions represent a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).



BiMOS Operational Amplifiers

With MOS/FET Input/ COS/MOS Output

FEATURES:

- MOS/FET input stage provides:
very high $Z_i = 1.5 T\Omega$ ($1.5 \times 10^{12}\Omega$) typ.
very low $I_i = 5 \text{ pA}$ typ. at 15-V operation
 2 pA typ. at 5-V operation
 - Common-mode input-voltage range includes negative supply rail; input terminals can be swung 0.5 V below negative supply rail
 - COS/MOS output stage permits signal swing to either (or both) supply rails
- } Ideal for single-supply applications

RCA-CA3130T, CA3130E, CA3130S, CA-3130AT, CA3130AS, CA3130AE, CA3130BT, and CA3130BS are integrated-circuit operational amplifiers that combine the advantages of both COS/MOS and bipolar transistors on a monolithic chip.

Gate-protected p-channel MOS/FET (PMOS) transistors are used in the input circuit to provide very-high-input impedance, very-low-input current, and exceptional speed performance. The use of PMOS field-effect transistors in the input stage results in common-mode input-voltage capability down to 0.5 volt below the negative-supply terminal, an important attribute in single-supply applications.

A complementary-symmetry MOS (COS/MOS) transistor-pair, capable of swinging the output voltage to within 10 millivolts of either supply-voltage terminal (at very high values of load impedance), is employed as the output circuit.

The CA3130 Series circuits operate at supply voltages ranging from 5 to 16 volts, or ± 2.5 to ± 8 volts when using split supplies. They can be phase compensated with a single external capacitor, and have terminals for adjustment of offset voltage for applications requiring offset-null capability. Terminal provisions are also made to permit strobing of the output stage.

The CA3130 Series is supplied in standard 8-lead TO-5 style packages (T suffix), 8-lead dual-in-line formed lead TO-5 style "DIL-CAN" packages (S suffix). The CA3130 is available in chip form (H suffix). The CA3130 and CA3130A are also available in the Mini-DIP 8-lead dual-in-line plastic

- Low V_{IO} : 2 mV max. (CA3130B)
- Wide BW: 15 MHz typ. (unity-gain crossover)
- High SR: 10 V/ μs typ. (unity-gain follower)
- High output current (I_O): 20 mA typ.
- High A_{OL} : 320,000 (110 dB) typ.
- Compensation with single external capacitor

APPLICATIONS:

- Ground-referenced single-supply amplifiers
- Fast sample-hold amplifiers
- Long-duration timers/monostables
- High-input-impedance comparators (ideal interface with digital COS/MOS)
- High-input-impedance wideband amplifiers
- Voltage followers (e.g., follower for single-supply D/A converter)
- Voltage regulators (permits control of output voltage down to zero volts)
- Peak detectors
- Single-supply full-wave precision rectifiers
- Photo-diode sensor amplifiers

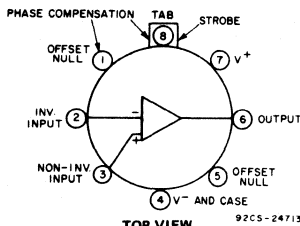
package (E suffix). All types operate over the full military-temperature range of -55°C to $+125^\circ\text{C}$. The CA3130B is intended for applications requiring premium-grade specifications. The CA3130A offers superior input characteristics over those of the CA3130.

Linear Integrated Circuits

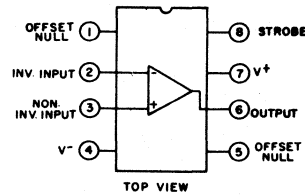
CA3130, CA3130A, CA3130B

ELECTRICAL CHARACTERISTICS at $T_A = -25^\circ\text{C}$, $V^+ = 15\text{ V}$, $V^- = 0\text{ V}$ (Unless otherwise specified)

CHARACTERISTIC	LIMITS									Units										
	CA3130B (T,S)			CA3130A (T,S,E)			CA3130 (T,S,E)													
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.											
Input Offset Voltage, $ V_{IO} $, $V^{\pm} = \pm 7.5\text{ V}$	-	0.8	2	-	2	5	-	8	15	mV										
Input Offset Current, $ I_{IO} $, $V^{\pm} = \pm 7.5\text{ V}$	-	0.5	10	-	0.5	20	-	0.5	30	μA										
Input Current, I_I , $V^{\pm} = \pm 7.5\text{ V}$	-	5	20	-	5	30	-	5	50	μA										
Large-Signal Voltage Gain, A_{OL} , $V_O = 10\text{ V}_{p-p}$, $R_L = 2\text{ k}\Omega$	100 k	320 k	-	50 k	320 k	-	50 k	320 k	-	V/V										
	100	110	-	94	110	-	94	110	-	dB										
Common-Mode Rejection Ratio, CMRR	86	100	-	80	90	-	70	90	-	dB										
Common-Mode Input-Voltage Range, V_{ICR}	0	-0.5 to 12	10	0	-0.5 to 12	10	0	-0.5 to 12	10	V										
Power-Supply Rejection Ratio, $\Delta V_{IO}/\Delta V^{\pm}$, $V^{\pm} = \pm 7.5\text{ V}$	-	32	100	-	32	150	-	32	320	$\mu\text{V}/\text{V}$										
Maximum Output Voltage:																				
											At $R_L = 2\text{ k}\Omega$									
											V_{OM}^-	-	0.002	0.01	-	0.002	0.01	-	0.002	0.01
At $R_L = \infty$																				
										V_{OM}^+	14.99	15	-	14.99	15	-	14.99	15	-	
V_{OM}^-	-	0	0.01	-	0	0.01	-	0	0.01											
Maximum Output Current:																				
I_{OM}^+ (Source) @ $V_O = 0\text{ V}$	12	22	45	12	22	45	12	22	45	mA										
I_{OM}^- (Sink) @ $V_O = 15\text{ V}$	12	20	45	12	20	45	12	20	45											
Supply Current, I^+ : $V_O = 7.5\text{ V}$, $R_L = \infty$																				
$V_O = 0\text{ V}$, $R_L = \infty$	-	10	15	-	10	15	-	10	15	mA										
$V_O = 0\text{ V}$, $R_L = \infty$	-	2	3	-	2	3	-	2	3											
Input Offset Voltage Temp. Drift, $\Delta V_{IO}/\Delta T^*$	-	5	-	-	10	-	-	10	-	$\mu\text{V}/^\circ\text{C}$										



S and T Suffixes



E Suffix

Fig. 1 - Functional diagrams for the CA3130 series.

CA3130, CA3130A, CA3130B

TYPICAL VALUES INTENDED ONLY FOR DESIGN GUIDANCE

CHARACTERISTIC	TEST CONDITIONS	CA3130B (T,S)	CA3130A (T,S,E)	CA3130 (T,S,E)	UNITS	
	$V^+ = +7.5\text{ V}$ $V^- = -7.5\text{ V}$ $T_A = 25^\circ\text{C}$ (Unless Otherwise Specified)					
Input Offset Voltage Adjustment Range	10 k Ω across Terms. 4 and 5 or 4 and 1	± 22	± 22	± 22	mV	
Input Resistance, R_I		1.5	1.5	1.5	T Ω	
Input Capacitance, C_I	$f = 1\text{ MHz}$	4.3	4.3	4.3	pF	
Equivalent Input Noise Voltage, e_n	BW = 0.2 MHz $R_S = 1\text{ M}\Omega^*$	23	23	23	μV	
Unity Gain Crossover Frequency, f_T	$C_C = 0$	15	15	15	MHz	
	$C_C = 47\text{ pF}$	4	4	4		
Slew Rate, SR:	Open Loop $C_C = 0$	30	30	30	V/ μs	
	Closed Loop $C_C = 56\text{ pF}$	10	10	10		
Transient Response:	$C_C = 56\text{ pF}$ $C_L = 25\text{ pF}$ $R_L = 2\text{ k}\Omega$ (Voltage Follower)	Rise Time, t_r	0.09	0.09	0.09	μs
		Overshoot	10	10	10	%
Settling Time (4 V_{p-p} Input to <0.1%)		1.2	1.2	1.2	μs	

* Although a 1-M Ω source is used for this test, the equivalent input noise remains constant for values of R_S up to 10 M Ω .

CHARACTERISTIC	TEST CONDITIONS	CA3130B (T,S)	CA3130A (T,S,E)	CA3130 (T,S,E)	UNITS
	$V^+ = 5\text{ V}$ $V^- = 0\text{ V}$ $T_A = 25^\circ\text{C}$ (Unless Otherwise Specified)				
Input Offset Voltage, V_{IO}		1	2	8	mV
Input Offset Current, I_{IO}		0.1	0.1	0.1	pA
Input Current, I_I		2	2	2	pA
Common-Mode Rejection Ratio, CMRR		100	90	80	dB
Large-Signal Voltage Gain, A_{OL}	$V_O = 4\text{ V}_{p-p}$ $R_L = 5\text{ k}\Omega$	100 k	100 k	100 k	V/V
		100	100	100	dB
Common-Mode Input Voltage Range, V_{ICR}		0 to 2.8	0 to 2.8	0 to 2.8	V
Supply Current, I^+	$V_O = 5\text{ V}$, $R_L = \infty$	300	300	300	μA
	$V_O = 2.5\text{ V}$, $R_L = \infty$	500	500	500	
Power Supply Rejection Ratio, $\Delta V_{IO}/\Delta V^+$		200	200	200	$\mu\text{V}/\text{V}$

Linear Integrated Circuits

CA3130, CA3130A, CA3130B

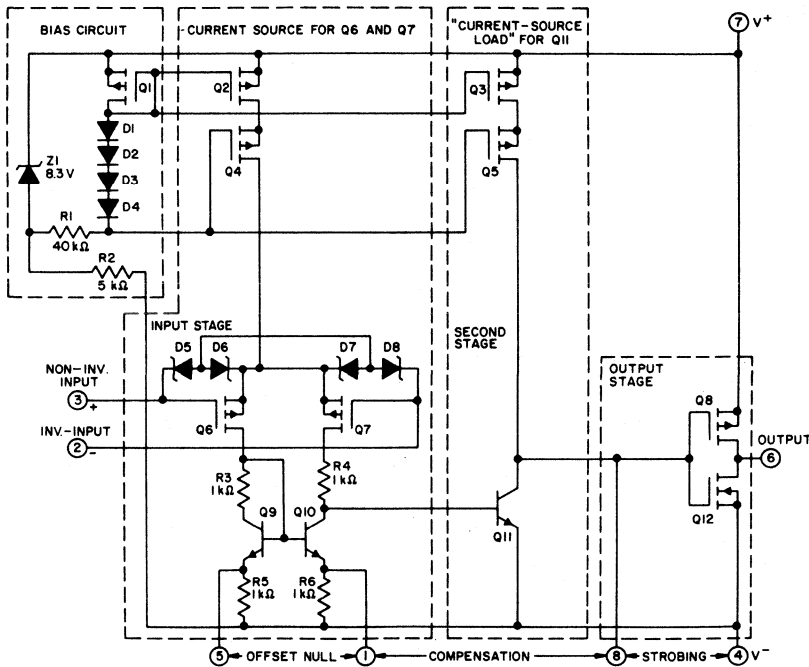
MAXIMUM RATINGS, Absolute-Maximum Values

DC SUPPLY VOLTAGE (Between V^+ and V^- Terminals)	16 V
DIFFERENTIAL-MODE INPUT VOLTAGE	± 8 V
COMMON-MODE DC INPUT VOLTAGE... ($V^+ + 8$ V) to ($V^- - 0.5$ V)	
INPUT-TERMINAL CURRENT	1 mA
DEVICE DISSIPATION:	
WITHOUT HEAT SINK -	
UP TO 55°C	630 mW
ABOVE 55°C	Derate linearly 6.67 mW/°C
WITH HEAT SINK -	
UP TO 90°C	1 W
ABOVE 90°C	Derate linearly 16.7 mW/°C

TEMPERATURE RANGE:

OPERATING (all types)	-55 to +125°C
STORAGE (all types)	-65 to +150°C
OUTPUT SHORT-CIRCUIT DURATION *	INDEFINITE
LEAD TEMPERATURE (DURING SOLDERING):	
AT DISTANCE 1/16 \pm 1/32 INCH (1.59 \pm 0.79 mm) FROM CASE	
FOR 10 SECONDS MAX.	+265°C

*Short circuit may be applied to ground or to either supply.



NOTE:
DIODES D5 THROUGH D8 PROVIDE GATE-OXIDE PROTECTION
FOR MOS/FET INPUT STAGE.

92CM-24714R1

Fig. 2 - Schematic diagram of the CA3130 Series.

CIRCUIT DESCRIPTION

Fig. 3 is a block diagram of the CA3130 Series COS/MOS Operational Amplifiers. The input terminals may be operated down to 0.5 V below the negative supply rail, and the output can be swung very close to either supply rail in many applications. Consequently, the CA3130 Series circuits are ideal for single-supply operation. Three Class A amplifier stages, having the individual gain capability and current consumption shown in Fig. 3, provide the total gain of the CA3130. A biasing circuit provides two potentials for common use in the first and

second stages. Term. 8 can be used both for phase compensation and to strobe the output stage into quiescence. When Term. 8 is tied to the negative supply rail (Term. 4) by mechanical or electrical means, the output potential at Term. 6 essentially rises to the positive supply-rail potential at Term. 7. This condition of essentially zero current drain in the output stage under the strobed "OFF" condition can only be achieved when the ohmic load resistance presented to the amplifier is very high (e.g., when the amplifier output is used to drive COS/MOS digital circuits in comparator applications).

CA3130, CA3130A, CA3130B

Input Stages—The circuit of the CA3130 is shown in Fig. 2. It consists of a differential-input stage using PMOS field-effect transistors (Q6, Q7) working into a mirror-pair of bipolar transistors (Q9, Q10) functioning as load resistors together with resistors R3 through R6. The mirror-pair transistors also function as a differential-to-single-ended converter to provide base drive to the second-stage bipolar transistor (Q11). Offset nulling, when desired, can be effected by connecting a 100,000-ohm potentiometer across Terms. 1 and 5 and the potentiometer slider arm to Term. 4. Cascode-connected PMOS transistors Q2, Q4 are the constant-current source for the input stage. The biasing circuit for the constant-current source is subsequently described. The small diodes D5 through D8 provide gate-oxide protection against high-voltage transients, e.g., including static electricity during handling for Q6 and Q7.

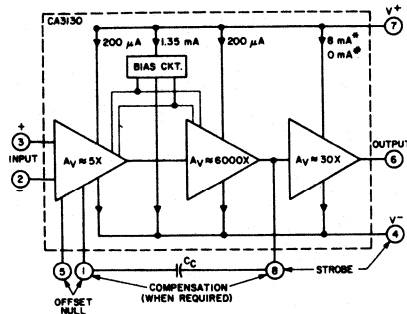
Second-Stage—Most of the voltage gain in the CA3130 is provided by the second amplifier stage, consisting of bipolar transistor Q11 and its cascode-connected load resistance provided by PMOS transistors Q3 and Q5. The source of bias potentials for these PMOS transistors is subsequently described. Miller-Effect compensation (roll-off) is accomplished by simply connecting a small capacitor between Terms. 1 and 8. A 47-picofarad capacitor provides sufficient compensation for stable unity-gain operation in most applications.

Bias-Source Circuit—At total supply voltages, somewhat above 8.3 volts, resistor R2 and zener diode Z1 serve to establish a voltage of 8.3 volts across the series-connected circuit, consisting of resistor R1, diodes D1 through D4, and PMOS transistor Q1. A tap at the junction of resistor R1 and diode D4 provides a gate-bias potential of about 4.5 volts for PMOS transistors Q4 and Q5 with respect to Term. 7. A potential of about 2.2 volts is developed across diode-connected PMOS transistor Q1 with respect to Term. 7 to provide gate bias for PMOS transistors Q2 and Q3. It

should be noted that Q1 is "mirror-connected"† to both Q2 and Q3. Since transistors Q1, Q2, Q3 are designed to be identical, the approximately 200-microampere current in Q1 establishes a similar current in Q2 and Q3 as constant-current sources for both the first and second amplifier stages, respectively.

At total supply voltages somewhat less than 8.3 volts, zener diode Z1 becomes non-conductive and the potential, developed across series-connected R1, D1-D4, and Q1, varies directly with variations in supply voltage. Consequently, the gate bias for Q4, Q5 and Q2, Q3 varies in accordance with supply-voltage variations. This variation results in deterioration of the power-supply-rejection ratio (PSRR) at total supply voltages below 8.3 volts. Operation at total supply voltages below about 4.5 volts results in seriously degraded performance.

Output Stage—The output stage consists of a drain-loaded inverting amplifier using COS/MOS transistors operating in the Class A mode. When operating into very high resistance loads, the output can be swung within millivolts of either supply rail. Because the output stage is a drain-loaded amplifier, its gain is dependent upon the load impedance. The transfer characteristics of the output stage for a load returned to the negative supply rail are shown in Fig. 6. Typical op-amp loads are readily driven by the output stage. Because large-signal excursions are non-linear, requiring feedback for good waveform reproduction, transient delays may be encountered. As a voltage follower, the amplifier can achieve 0.01 per cent accuracy levels, including the negative supply rail.



TOTAL SUPPLY VOLTAGE (FOR INDICATED GAIN) = 15 V
 * WITH INPUT TERMINALS BIASED SO THAT TERM 6 POTENTIAL IS +7.5 V ABOVE TERM. 4.
 † WITH OUTPUT TERMINAL DRIVEN TO EITHER SUPPLY RAIL.
 92CS-24715

Fig. 3 — Block diagram of the CA3130 Series.

†For general information on the characteristics of COS/MOS transistor-pairs in linear-circuit applications, see File No. 619, data bulletin on CA3600E "COS/MOS Transistor Array".

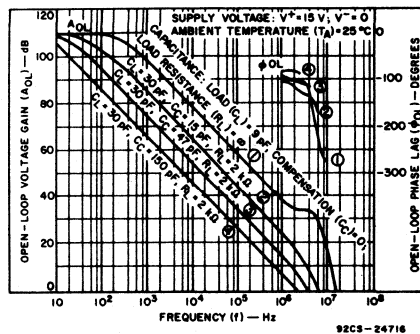


Fig. 4 — Open-loop voltage gain and phase shift vs. frequency for various values of C_L , C_C , and R_L .

Linear Integrated Circuits

CA3130, CA3130A, CA3130B

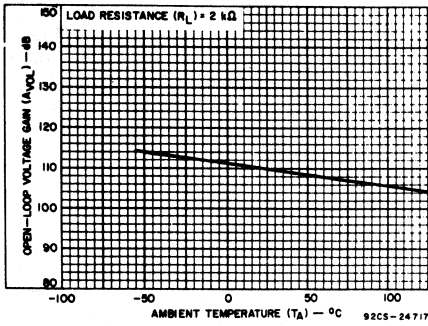


Fig. 5 - Open-loop gain vs. temperature.

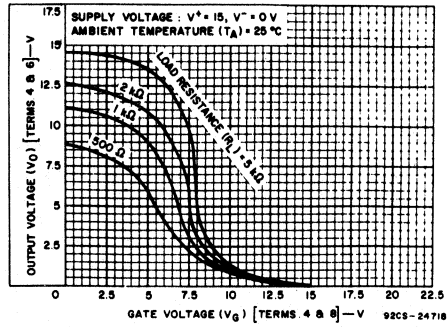


Fig. 6 - Voltage transfer characteristics of COS/MOS output stage.

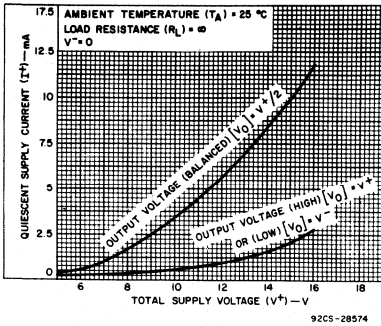


Fig. 7 - Quiescent supply current vs. supply voltage.

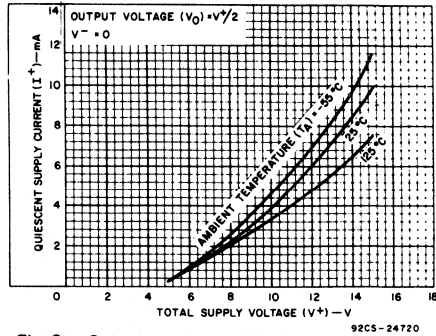


Fig. 8 - Quiescent supply current vs. supply voltage at several temperatures.

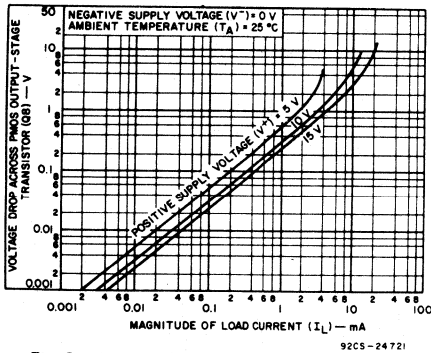


Fig. 9 - Voltage across PMOS output transistor (Q8) vs. load current.

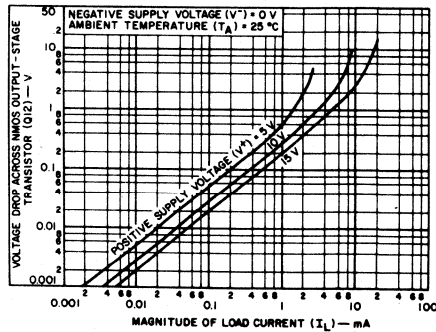


Fig. 10 - Voltage across NMOS output transistor (Q12) vs. load current.

Input Current Variation with Common-Mode Input Voltage

As shown in the Table of Electrical Characteristics, the input current for the CA3130 Series Op-Amps is typically 5 pA at $T_A = 25^\circ\text{C}$ when terminals 2 and 3 are at a common-mode potential of +7.5 volts with respect to negative supply Terminal 4. Fig. 11 contains data showing the variation of input current as a function of common-mode input voltage at $T_A = 25^\circ\text{C}$. These data show that circuit designers can advantageously exploit these characteristics to design circuits which typically require an input current of less than 1 pA, provided the common-mode input voltage does not exceed 2 volts. As previously noted, the input current is essentially the result of the leakage current through the

gate-protection diodes in the input circuit and, therefore, a function of the applied

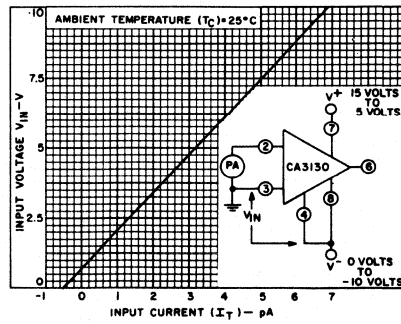


Fig. 11 - Input current vs. common-mode voltage.

voltage. Although the finite resistance of the glass terminal-to-case insulator of the TO-5 package also contributes an increment of leakage current, there are useful compensating factors. Because the gate-protection network functions as if it is connected to Terminal 4 potential, and the TO-5 case of the CA3130 is also internally tied to Terminal 4, input terminal 3 is essentially "guarded" from spurious leakage currents.

Offset Nulling

Offset-voltage nulling is usually accomplished with a 100,000-ohm potentiometer connected across Terms. 1 and 5 and with the potentiometer slider arm connected to Term. 4. A fine offset-null adjustment usually can be effected with the slider arm positioned in the mid-point of the potentiometer's total range.

Input-Current Variation with Temperature

The input current of the CA3130 Series circuits is typically 5 pA at 25°C. The major portion of this input current is due to leakage current through the gate-protective diodes in the input circuit. As with any semiconductor-junction device, including op amps with a junction-FET input stage, the leakage current approximately doubles for every 10°C increase in temperature. Fig.12 provides data on the typical variation of input bias current as a function of temperature in the CA3130.

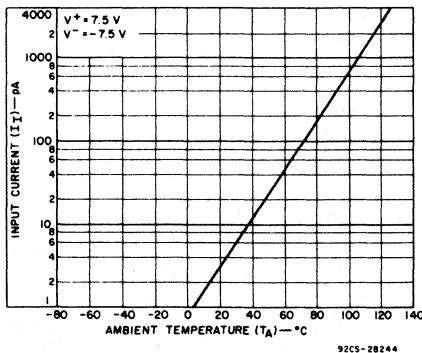


Fig.12 - Input current vs. ambient temperature.

In applications requiring the lowest practical input current and incremental increases in current because of "warm-up" effects, it is suggested that an appropriate heat sink be used with the CA3130. In addition, when "sinking" or "sourcing" significant output current the chip temperature increases, causing an increase in the input current. In such cases, heat-sinking can also very markedly reduce and stabilize input current variations.

Input-Offset-Voltage (V_{IO}) Variation with DC Bias vs. Device Operating Life

It is well known that the characteristics of a MOS/FET device can change slightly when a dc gate-source bias potential is applied to the device for extended time periods. The magni-

tude of the change is increased at high temperatures. Users of the CA3130 should be alert to the possible impacts of this effect if the application of the device involves extended operation at high temperatures with a significant differential dc bias voltage applied across Terms. 2 and 3. Fig.13 shows typical data pertinent to shifts in offset voltage encountered with CA3130 devices (TO-5 package) during life testing. At lower temperatures (TO-5 and plastic), for example at 85°C, this change in voltage is considerably less. In typical linear applications where the differential voltage is small and symmetrical, these incremental changes are of about the same magnitude as those encountered in an operational amplifier employing a bipolar transistor input stage. The two-volt dc differential voltage example represents conditions when the amplifier output stage is "toggled", e.g., as in comparator applications.

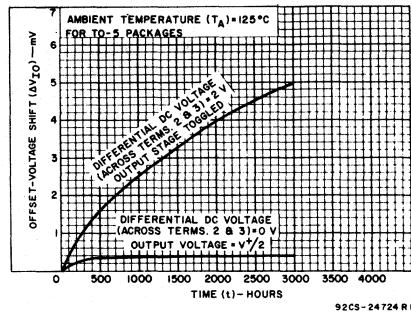


Fig.13 - Typical incremental offset-voltage shift vs. operating life.

Power-Supply Considerations

Because the CA3130 is very useful in single-supply applications, it is pertinent to review some considerations relating to power-supply current consumption under both single- and dual-supply service. Figs. 14a and 14b show the CA3130 connected for both dual- and single-supply operation.

Dual-supply operation: When the output voltage at Term. 6 is zero-volts, the currents supplied by the two power supplies are equal. When the gate terminals of Q8 and Q12 are driven increasingly positive with respect to ground, current flow through Q12 (from the negative supply) to the load is increased and current flow through Q8 (from the positive supply) decreases correspondingly. When the gate terminals of Q8 and Q12 are driven increasingly negative with respect to ground, current flow through Q8 is increased and current flow through Q12 is decreased accordingly.

Single-supply operation: Initially, let it be assumed that the value of R_L is very high (or disconnected), and that the input-terminal bias (Terms. 2 and 3) is such that the output terminal (No. 6) voltage is at $V^+/2$, i.e.,

CA3130, CA3130A, CA3130B

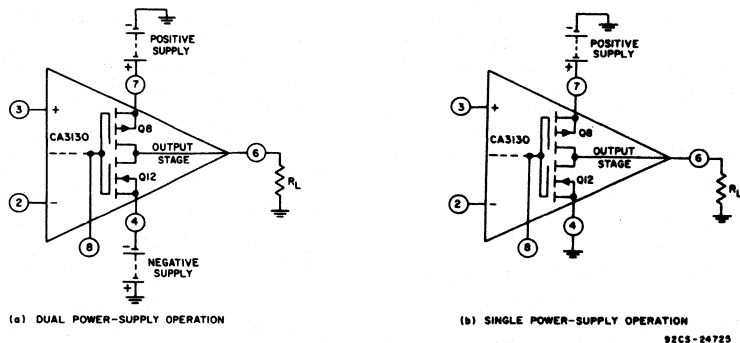


Fig. 14 - CA3130 output stage in dual and single power-supply operation.

the voltage-drops across Q8 and Q12 are of equal magnitude. Fig. 7 shows typical quiescent supply-current vs. supply-voltage for the CA3130 operated under these conditions. Since the output stage is operating as a Class A amplifier, the supply-current will remain constant under dynamic operating conditions as long as the transistors are operated in the linear portion of their voltage-transfer characteristics (see Fig. 6). If either Q8 or Q12 are swung out of their linear regions toward cut-off (a non-linear region), there will be a corresponding reduction in supply-current. In the extreme case, e.g., with Term. 8 swung down to ground potential (or tied to ground), NMOS transistor Q12 is completely cut off and the supply-current to series-connected transistors Q8, Q12 goes essentially to zero. The two preceding stages in the CA3130, however, continue to draw modest supply-current (see the lower curve in Fig. 7) even though the output stage is strobed off. Fig. 14a shows a dual-supply arrangement for the output stage that can also be strobed off, assuming $R_L = \infty$, by pulling the potential of Term. 8 down to that of Term. 4.

Let it now be assumed that a load-resistance of nominal value (e.g., 2 kilohms) is connected between Term. 6 and ground in the circuit of Fig. 14b. Let it further be assumed again that the input-terminal bias (Terms. 2 and 3) is such that the output terminal (No. 6) voltage is a $V^+/2$. Since PMOS transistor Q8 must now supply quiescent current to both R_L and transistor Q12, it should be apparent that under these conditions the supply-current must increase as an inverse function of the R_L magnitude. Fig. 9 shows the voltage-drop across PMOS transistor Q8 as a function of load current at several supply-voltages. Fig. 6 shows the voltage-transfer characteristics of the output stage for several values of load resistance.

Wideband Noise

From the standpoint of low-noise performance considerations, the use of the CA3130 is most advantageous in applications where in the source resistance of the input signal is

in the order of 1 megohm or more. In this case, the total input-referred noise voltage is typically only $23 \mu\text{V}$ when the test-circuit amplifier of Fig. 15 is operated at a total supply voltage of 15 volts. This value of total input-referred noise remains essentially constant, even though the value of source resistance is raised by an order of magnitude. This characteristic is due to the fact that reactance of the input capacitance becomes a significant factor in shunting the source resistance. It should be noted, however, that for values of source resistance very much greater than 1 megohm, the total noise voltage generated can be dominated by the thermal noise contributions of both the feedback and source resistors.

TYPICAL APPLICATIONS

Voltage Followers

Operational amplifiers with very high input resistances, like the CA3130, are particularly suited to service as voltage followers. Fig. 16 shows the circuit of a classical voltage follower, together with pertinent waveforms using the CA3130 in a split-supply configuration.

A voltage follower, operated from a single supply, is shown in Fig. 17, together with related waveforms. This follower circuit is

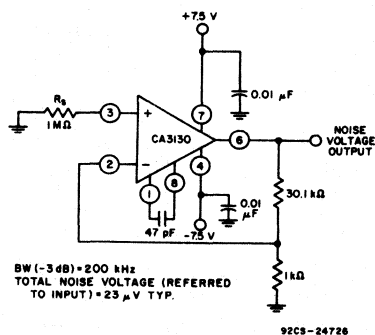
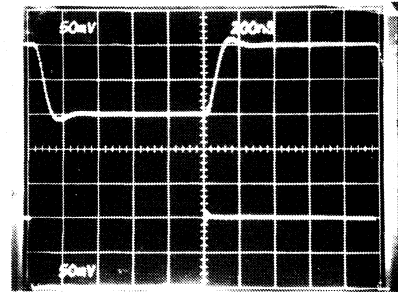
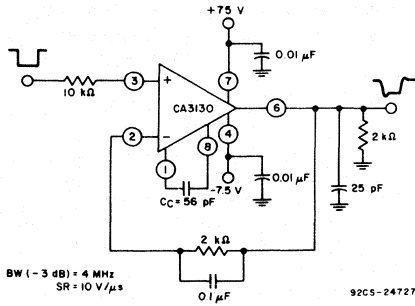


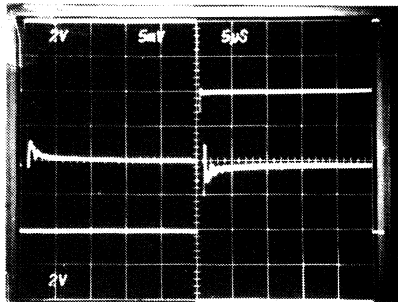
Fig. 15 - Test-circuit amplifier (30-dB gain) used for wideband noise measurements.

Operational Amplifiers

CA3130, CA3130A, CA3130B



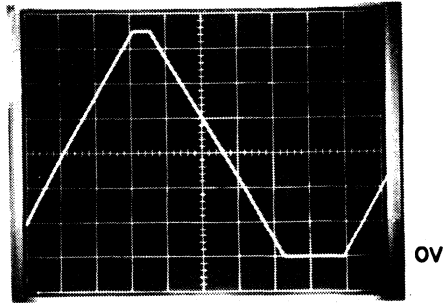
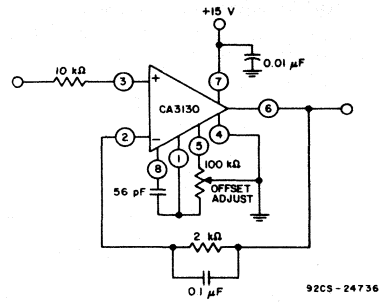
Top Trace: Output
Bottom Trace: Input
(a) Small-signal response (50 mV/div. and 200 ns/div.)



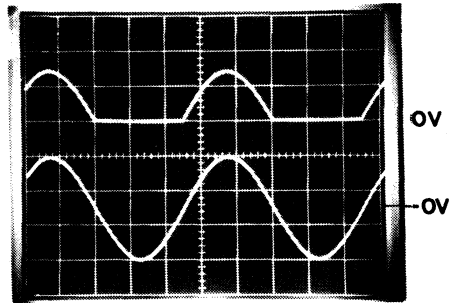
Top Trace: Output signal (2 V/div. and 5 μs/div.)
Center Trace: Difference signal (5 mV/div. and 5 μs/div.)
Bottom Trace: Input signal (2 V/div. and 5 μs/div.)
(b) Input-output difference signal showing settling time (Measurement made with Tektronix 7A13 differential amplifier)

Fig. 16 — Split-supply voltage follower with associated waveforms.

linear over a wide dynamic range, as illustrated by the reproduction of the output waveform in Fig. 17a, with input-signal ramping. The waveforms in Fig. 17b show that the follower does not lose its input-to-output phase-sense, even though the input is



(a) Output-waveform with input-signal ramping (2 V/div. and 500 μs/div.)



Top Trace: Output (5 V/div. and 200 μs/div.)
Bottom Trace: Input (5 V/div. and 200 μs/div.)
(b) Output-waveform with ground-reference sine-wave input

Fig. 17 — Single-supply voltage-follower with associated waveforms. (e.g., for use in single-supply D/A converter; see Fig. 9 in ICAN-6080).

being swung 7.5 volts below ground potential. This unique characteristic is an important attribute in both operational amplifier and comparator applications. Fig. 17b also shows the manner in which the COS/MOS output stage permits the output signal to swing down to the negative supply-rail potential (i.e., ground in the case shown). The digital-to-analog converter (DAC) circuit, described in the following section, illustrates the practical use of the CA3130 in a single-supply voltage-follower application.

Linear Integrated Circuits

CA3130, CA3130A, CA3130B

9-Bit COS/MOS DAC

A typical circuit of a 9-bit Digital-to-Analog Converter (DAC)* is shown in Fig.18. This system combines the concepts of multiple-switch COS/MOS IC's, a low-cost ladder network of discrete metal-oxide-film resistors, a CA3130 op amp connected as a follower, and an inexpensive monolithic regulator in a simple single power-supply arrangement. An additional feature of the DAC is that it is readily interfaced with COS/MOS input logic, e.g., 10-volt logic levels are used in the circuit of Fig.18.

of one per cent tolerance metal-oxide film resistors. The five arms requiring the highest accuracy are assembled with series and parallel combinations of 806,000-ohm resistors from the same manufacturing lot.

A single 15-volt supply provides a positive bus for the CA3130 follower amplifier and feeds the CA3085 voltage regulator. A "scale-adjust" function is provided by the regulator output control, set to a nominal 10-volt level in this system. The line-voltage regulation (approximately 0.2%) permits a 9-bit accuracy to be maintained with varia-

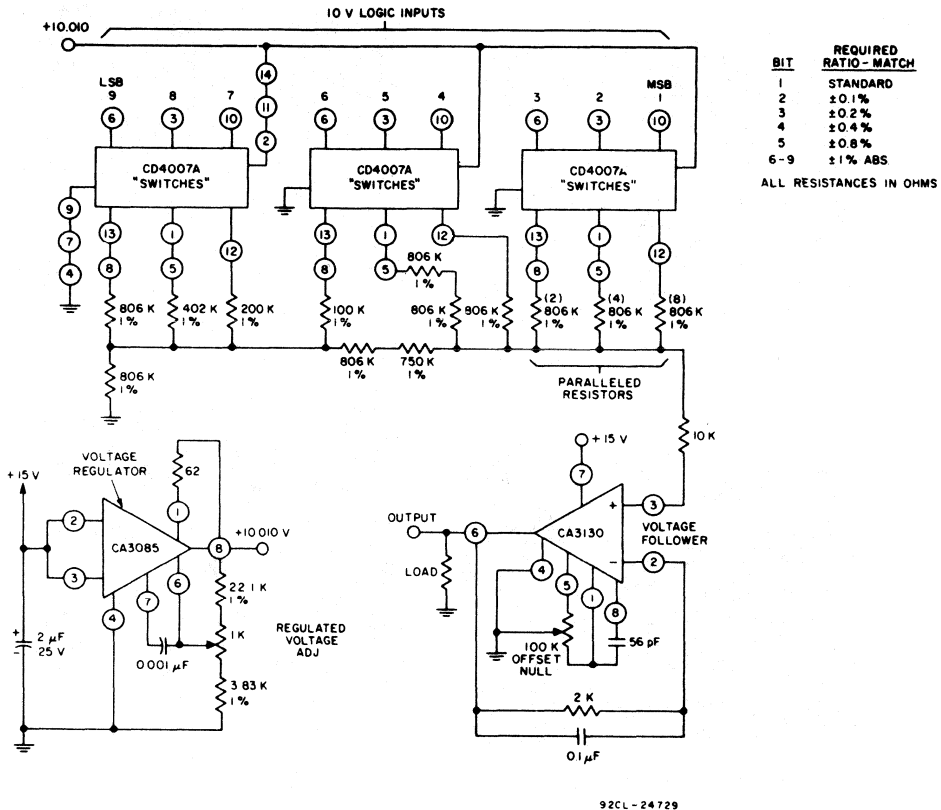


Fig.18 - 9-bit DAC using COS/MOS digital switches and CA3130.

The circuit uses an R/2R voltage-ladder network, with the output potential obtained directly by terminating the ladder arms at either the positive or the negative power-supply terminal. Each CD4007A contains three "inverters", each "inverter" functioning as a single-pole double-throw switch to terminate an arm of the R/2R network at either the positive or negative power-supply terminal. The resistor ladder is an assembly

tions of several volts in the supply. The flexibility afforded by the COS/MOS building blocks simplifies the design of DAC systems tailored to particular needs.

Single-Supply, Absolute-Value, Ideal Full-Wave Rectifier

The absolute-value circuit using the CA3130 is shown in Fig. 19. During positive excursions, the input signal is fed through the feedback network directly to the output. Simultaneously, the positive excursion of the input signal also drives the output terminal (No. 6) of the inverting amplifier in a

*Digital-to-Analog Conversion Using the RCA-CD4007A COS/MOS IC", Application Note ICAN-6080.

negative-going excursion such that the 1N914 diode effectively disconnects the amplifier from the signal path. During a negative-going excursion of the input signal, the CA3130 functions as a normal inverting amplifier with a gain equal to $-R2/R1$. When the equality of the two equations shown in Fig. 19 is satisfied, the full-wave output is symmetrical.

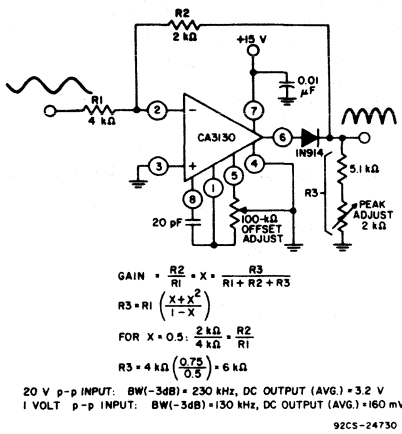
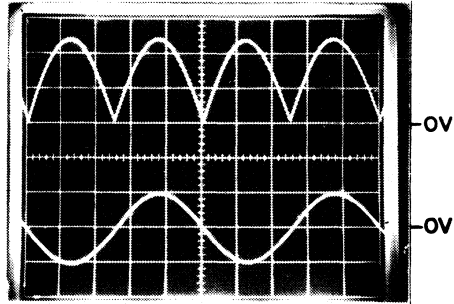


Fig. 19 — Single-supply, absolute-value, ideal full-wave rectifier with associated waveforms.

Error-Amplifier in Regulated-Power Supplies

The CA3130 is an ideal choice for error-amplifier service in regulated power supplies since it can function as an error-amplifier when the regulated output voltage is required to approach zero. Fig. 21 shows the schematic diagram of a 40-mA power supply capable of providing regulated output volt-

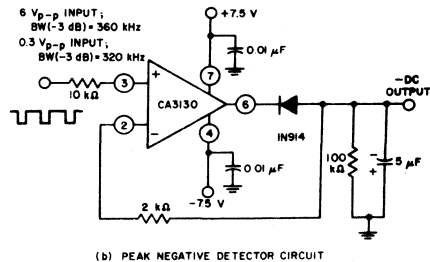
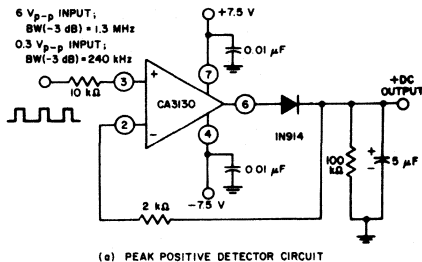


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Top Trace: Output signal (2 V/div.)
 Bottom Trace: Input signal (10 V/div.)
 Time base on both traces: 0.2 ms/div.

Peak Detectors

Peak-detector circuits are easily implemented with the CA3130, as illustrated in Fig. 20 for both the peak-positive and the peak-negative circuit. It should be noted that with large-signal inputs, the bandwidth of the peak-negative circuit is much less than that of the peak-positive circuit. The second stage of the CA3130 limits the bandwidth in this case. Negative-going output-signal excursion requires a positive-going signal excursion at the collector of transistor Q11, which is loaded by the intrinsic capacitance of the associated circuitry in this mode. On the other hand, during a negative-going signal excursion at the collector of Q11, the transistor functions in an active "pull-down" mode so that the intrinsic capacitance can be discharged more expeditiously.



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Fig. 20 — Peak-detector circuits.

age by continuous adjustment over the range from 0 to 13 volts. Q3 and Q4 in IC2 (a CA3086 transistor-array IC) function as zeners to provide supply-voltage for the CA3130 comparator (IC1). Q1, Q2, and Q5 in IC2 are configured as a low impedance, temperature-compensated source of adjustable reference voltage for the error amplifier. Transistors Q1, Q2, Q3, and Q4 in IC3 (another CA3086 transistor-array IC) are connected in parallel as the series-pass element. Transistor Q5 in IC3 functions as a current-limiting device by diverting base drive from the series-pass transistors, in accordance with the adjustment of resistor R2.

Fig. 22 contains the schematic diagram of a regulated power-supply capable of providing regulated output voltage by continuous ad-

Linear Integrated Circuits

CA3130, CA3130A, CA3130B

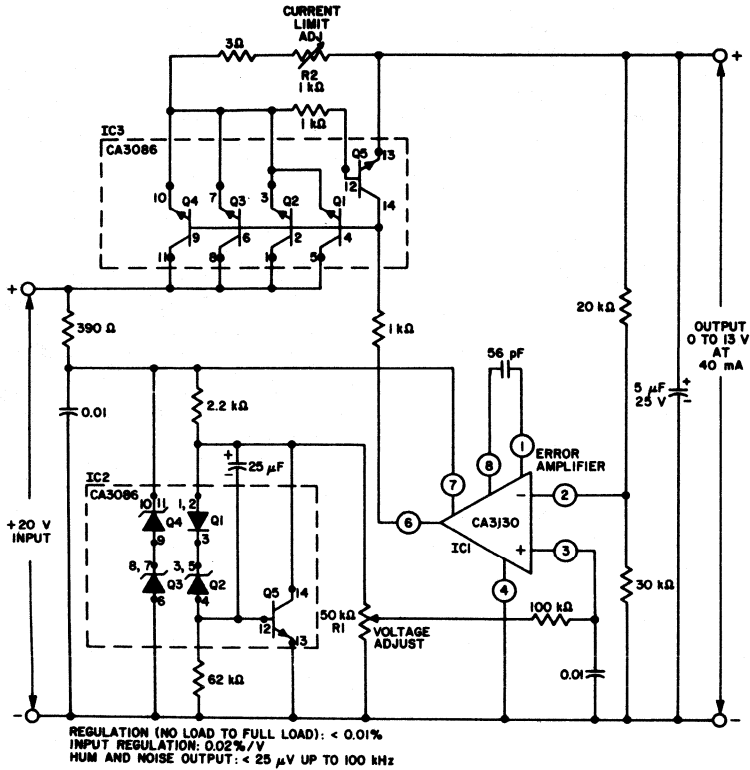


Fig. 21 — Voltage regulator circuit (0 to 13 V at 40 ma).

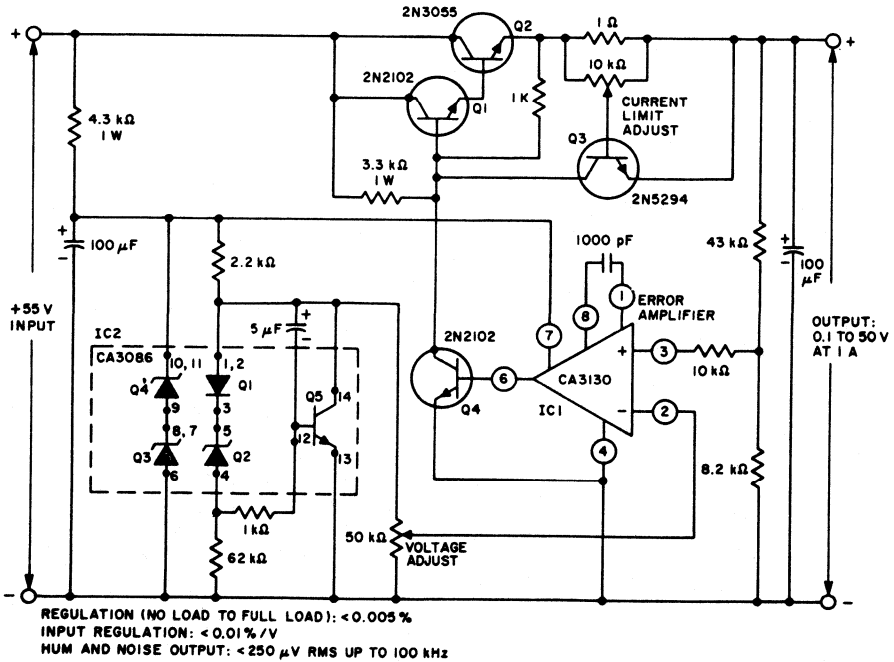


Fig. 22 — Voltage regulator circuit (0.1 to 50 V at 1 A).

CA3130, CA3130A, CA3130B

justment over the range from 0.1 to 50 volts and currents up to 1 ampere. The error amplifier (IC1) and circuitry associated with IC2 function as previously described, although the output of IC1 is boosted by a discrete transistor (Q4) to provide adequate base drive for the Darlington-connected series-pass transistors Q1, Q2. Transistor Q3 functions in the previously described current-limiting circuit.

Multivibrators

The exceptionally high input resistance presented by the CA3130 is an attractive feature for multivibrator circuit design because it permits the use of timing circuits with high R/C ratios. The circuit diagram of a pulse generator (astable multivibrator), with provisions for independent control of the "on" and "off" periods, is shown in Fig. 23. Resistors R1 and R2 are used to bias the CA3130 to the mid-point of the supply-voltage and R3 is the feedback resistor. The pulse repetition rate is selected by positioning S1 to the desired position and the rate remains essentially constant when the resistors which determine "on-period" and "off-period" are adjusted.

Function Generator

Fig. 24 contains a schematic diagram of a function generator using the CA3130 in the integrator and threshold detector functions. This circuit generates a triangular or square-

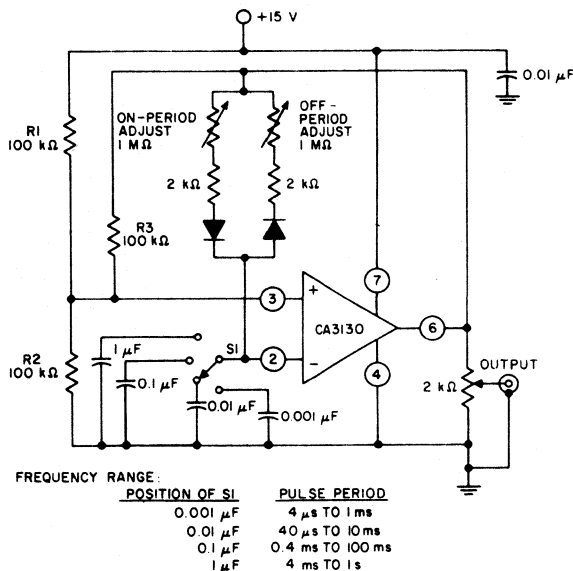
wave output that can be swept over a 1,000,000:1 range (0.1 Hz to 100 kHz) by means of a single control, R1. A voltage-control input is also available for remote sweep-control.

The heart of the frequency-determining system is an operational-transconductance-amplifier (OTA)*, IC1, operated as a voltage-controlled current-source. The output, I_O , is a current applied directly to the integrating capacitor, C1, in the feedback loop of the integrator IC2, using a CA3130, to provide the triangular-wave output. Potentiometer R2 is used to adjust the circuit for slope symmetry of positive-going and negative-going signal excursions.

Another CA3130, IC3, is used as a controlled switch to set the excursion limits of the triangular output from the integrator circuit. Capacitor C2 is a "peaking adjustment" to optimize the high-frequency square-wave performance of the circuit.

Potentiometer R3 is adjustable to perfect the "amplitude symmetry" of the square-wave output signals. Output from the threshold detector is fed back via resistor R4 to the input of IC1 so as to toggle the current source from plus to minus in generating the linear triangular wave.

*See File No. 475 and ICAN-6668.



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Fig. 23 — Pulse generator (astable multivibrator) with provisions for independent control of "ON" and "OFF" periods.

CA3130, CA3130A, CA3130B

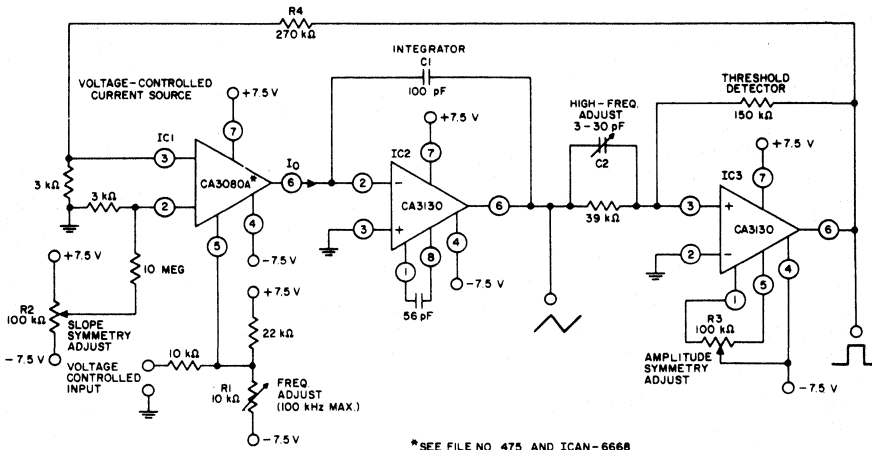


Fig. 24 - Function generator (frequency can be varied 1,000,000/1 with a single control).

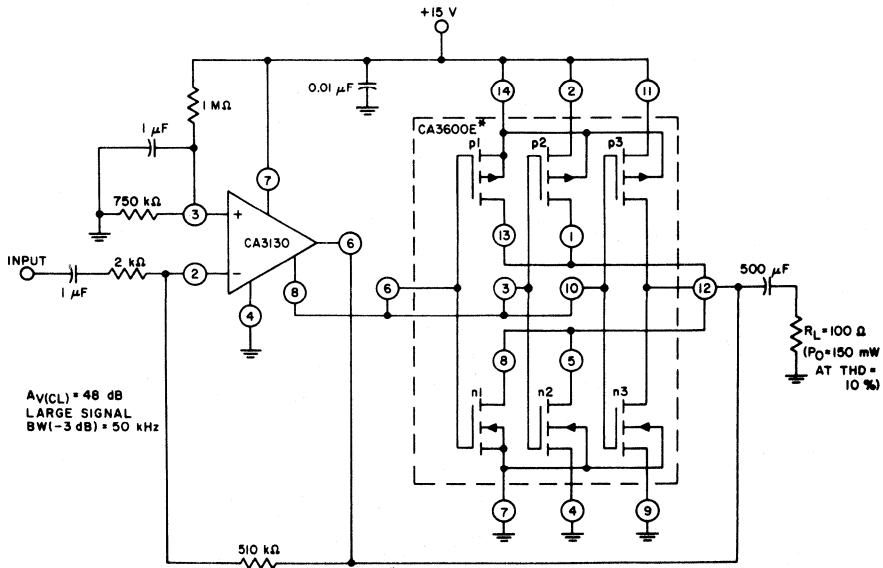
Operation with Output-Stage Power-Booster

The current-sourcing and -sinking capability of the CA3130 output stage is easily supplemented to provide power-boost capability. In the circuit of Fig. 25, three COS/MOS transistor-pairs in a single CA3600E* IC array are shown parallel connected with the output stage in the CA3130. In the Class A mode of CA3600E shown, a typical device consumes 20 mA of supply current at 15-V operation.

This arrangement boosts the current-handling capability of the CA3130 output stage by about 2.5X.

The amplifier circuit in Fig. 25 employs feedback to establish a closed-loop gain of 48 dB. The typical large-signal bandwidth (-3 dB) is 50 kHz.

*See File No. 619 for technical information.

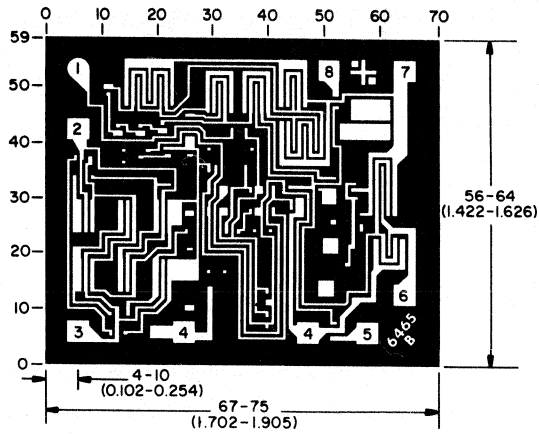


NOTE:
TRANSISTORS p1, p2, p3 AND n1, n2, n3 ARE
PARALLEL-CONNECTED WITH Q8 AND Q12,
RESPECTIVELY, OF THE CA3130

*SEE FILE NO. 619

Fig. 25 - COS/MOS transistor array (CA3600E) connected as power-booster in the output stage of the CA3130.

CA3130, CA3130A, CA3130B



92CS-33311

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

The photographs and dimensions represent a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

Dimensions and Pad Layout for CA3130H.

CA3140, CA3140A, CA3140B Types



BiMOS Operational Amplifiers

With MOS/FET Input/Bipolar Output

FEATURES:

- **MOS/FET Input Stage**
 - (a) Very high input impedance (Z_{IN}) — 1.5 T Ω typ.
 - (b) Very low input current (I_I) — 10 pA typ. at ± 15 V
 - (c) Low input-offset voltage (V_{IO}) — to 2 mV max.
 - (d) Wide common-mode input-voltage range (V_{ICR})— can be swung 0.5 volt below negative supply-voltage rail
 - (e) Output swing complements input common-mode range
 - (f) Rugged input stage — bipolar diode protected

The CA3140B, CA3140A, and CA3140 are integrated-circuit operational amplifiers that combine the advantages of high-voltage PMOS transistors with high-voltage bipolar transistors on a single monolithic chip. Because of this unique combination of technologies, this device can now provide designers, for the first time, with the special performance features of the CA3130 COS/MOS operational amplifiers and the versatility of the 741 series of industry-standard operational amplifiers.

The CA3140, CA3140A, and CA3140 BiMOS operational amplifiers feature gate-protected MOS/FET (PMOS) transistors in the input circuit to provide very-high-input impedance, very-low-input current, and high-speed performance. The CA3140B operates at supply voltages from 4 to 44 volts; the CA3140A and CA3140 from 4 to 36 volts (either single or dual supply). These operational amplifiers are internally phase-compensated to achieve stable operation in unity-gain follower operation, and, additionally, have access terminals for a supplementary external capacitor if additional frequency roll-off is desired. Terminals are also provided for use in applications requiring input offset-voltage nulling. The use of PMOS field-effect transistors in the input stage results in common-mode input-voltage capability down to 0.5 volt below the negative-supply terminal, an important attribute for single-supply applications. The output stage uses bipolar transistors and includes built-in protection against damage from load-terminal short-circuiting to either supply-rail or to ground.

The CA3140 Series has the same 8-lead terminal pin-out used for the "741" and other industry-standard operational amplifiers. They are supplied in either the standard 8-lead TO-5 style package (T suffix), or in the 8-lead dual-in-line formed-lead TO-5 style package "DIL-CAN" (S suffix). The CA3140 is available in chip form (H suffix). The CA3140A and CA3140 are also available in an 8-lead dual-in-line

- Directly replaces industry type 741 in most applications
- Includes numerous industry operational amplifier categories such as general-purpose, FET input, wideband (high slew rate)
- Operation from 4-to-44 volts
Single or Dual supplies
- Internally compensated
- Characterized for ± 15 -volt operation and for TTL supply systems with operation down to 4 volts
- Wide bandwidth — 4.5 MHz unity gain at ± 15 V or 30 V; 3.7 MHz at 5 V
- High voltage-follower slew rate — 9 V/ μ s
- Fast setting time — 1.4 μ s typ. to 10 mV with a 10-V_{p-p} signal
- Output swings to within 0.2 volt of negative supply
- Strobable output stage

APPLICATIONS:

- Ground-referenced single-supply amplifiers in automobile and portable instrumentation
- Sample and hold amplifiers
- Long-duration timers/multivibrators (microseconds—minutes—hours)
- Photocurrent instrumentation
- Peak detectors ■ Active filters
- Comparators
- Interface in 5 V TTL systems & other low-supply voltage systems
- All standard operational amplifier applications
- Function generators ■ Tone controls
- Power supplies ■ Portable instruments
- Intrusion alarm systems

CA3140, CA3140A, CA3140B Types

plastic package (Mini-DIP-E suffix). The CA3140B is intended for operation at supply voltages ranging from 4 to 44 volts, for applications requiring premium-grade specifications. The CA3140A and CA3140

are for operation at supply voltages up to 36 volts (± 18 volts). All types can be operated safely over the temperature range from -55°C to $+125^{\circ}\text{C}$.

TYPICAL ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	TEST CONDITIONS		CA3140B (T,S)	CA3140A (T,S,E)	CA3140 (T,S,E)	UNITS
	$V^+ = +15\text{ V}$ $V^- = -15\text{ V}$ $T_A = 25^{\circ}\text{C}$					
Input Offset Voltage Adjustment Resistor	Typ. Value of Resistor Between Term. 4 and 5 or 4 and 1 to Adjust Max. V_{IO}		43	18	4.7	$\text{k}\Omega$
Input Resistance	R_I		1.5	1.5	1.5	$\text{T}\Omega$
Input Capacitance	C_I		4	4	4	pF
Output Resistance	R_O		60	60	60	Ω
Equivalent Wideband Input Noise Voltage (See Fig. 39)	e_n	$\text{BW} = 140\text{ kHz}$ $R_S = 1\text{ M}\Omega$	48	48	48	μV
Equivalent Input Noise Voltage (See Fig. 10)	e_n	$f = 1\text{ kHz}$ $R_S =$	40	40	40	$\text{nV}/\sqrt{\text{Hz}}$
		$f = 10\text{ kHz}$ $100\ \Omega$	12	12	12	
Short-Circuit Current to Opposite Supply	Source I_{OM}^+		40	40	40	mA
	Sink I_{OM}^-		18	18	18	mA
Gain-Bandwidth Product, (See Figs. 5 & 18)	f_T		4.5	4.5	4.5	MHz
Slew Rate, (See Fig. 6)	SR		9	9	9	$\text{V}/\mu\text{s}$
Sink Current From Terminal 8 To Terminal 4 to Swing Output Low			220	220	220	μA
Transient Response: Rise Time Overshoot (See Fig. 37)	t_r	$R_L = 2\text{ k}\Omega$ $C_L = 100\text{ pF}$	0.08	0.08	0.08	μs
			10	10	10	%
Settling Time at 10 V_{p-p} , (See Fig. 17)	1 mV	$R_L = 2\text{ k}\Omega$ $C_L = 100\text{ pF}$ Voltage Follower	4.5	4.5	4.5	μs
	10 mV		1.4	1.4	1.4	

Linear Integrated Circuits

CA3140, CA3140A, CA3140B Types

ELECTRICAL CHARACTERISTICS FOR EQUIPMENT DESIGN

At $V^+ = 15\text{ V}$, $V^- = 15\text{ V}$, $T_A = 25^\circ\text{C}$ Unless Otherwise Specified

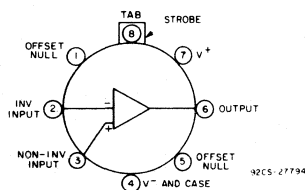
CHARACTERISTIC	LIMITS									UNITS
	CA3140B			CA3140A			CA3140			
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage, $ V_{IO} $	-	0.8	2	-	2	5	-	5	15	mV
Input Offset Current, $ I_{IO} $	-	0.5	10	-	0.5	20	-	0.5	30	pA
Input Current, I_i	-	10	30	-	10	40	-	10	50	pA
Large-Signal Voltage Gain, A_{OL} [•] (See Figs. 4,18)	50 k	100 k	-	20 k	100 k	-	20 k	100 k	-	V/V
	94	100	-	86	100	-	86	100	-	dB
Common-Mode Rejection Ratio, CMRR (See Fig.9)	-	20	50	-	32	320	-	32	320	$\mu\text{V/V}$
	86	94	-	70	90	-	70	90	-	dB
Common-Mode Input-Voltage Range, V_{ICR} (See Fig.20)	-15	-15.5 to +12.5	12	-15	-15.5 to +12.5	12	-15	-15.5 to +12.5	11	V
Power-Supply Rejection Ratio, PSRR (See Fig.11)	-	32	100	-	100	150	-	100	150	$\mu\text{V/V}$
	80	90	-	76	80	-	76	80	-	dB
Max. Output Voltage [■] (See Figs.13,20)	V_{OM}^+	+12	13	-	+12	13	-	+12	13	V
	V_{OM}^-	-14	-14.4	-	-14	-14.4	-	-14	-14.4	
Supply Current, I^+ (See Fig.7)	-	4	6	-	4	6	-	4	6	mA
Device Dissipation, P_D	-	120	180	-	120	180	-	120	180	mW
Input Offset Voltage Temp. Drift, $\Delta V_{IO}/\Delta T$	-	5	-	-	6	-	-	8	-	$\mu\text{V}/^\circ\text{C}$
Max. Output Voltage, [★]	V_{OM}^+	+19	+19.5	-	-	-	-	-	-	V
	V_{OM}^-	-21	-21.4	-	-	-	-	-	-	
Large-Signal Voltage Gain, A_{OL} [★]	20 k	50 k	-	-	-	-	-	-	-	V/V
	86	94	-	-	-	-	-	-	-	dB

• At $V_O = 26\text{V}_{\text{p-p}}$, $+12\text{V}$, -14V and $R_L = 2\text{ k}\Omega$.

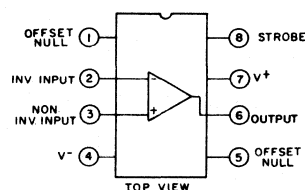
■ At $R_L = 2\text{ k}\Omega$.

◆ At $V_O = +19\text{ V}$, -21 V , and $R_L = 2\text{ k}\Omega$.

★ At $V^+ = 22\text{ V}$, $V^- = 22\text{ V}$.



TOP VIEW
S and T Suffixes



TOP VIEW
E Suffix

Fig. 1 - Functional diagrams of the CA3140 series.

92CS-29086

CA3140, CA3140A, CA3140B Types

MAXIMUM RATINGS, Absolute-Maximum Values:

	CA3140, CA3140A	CA3140B
DC SUPPLY VOLTAGE (BETWEEN V ⁺ AND V ⁻ TERMINALS)	36 V	44 V
DIFFERENTIAL-MODE INPUT VOLTAGE	± 8 V	± 8 V
COMMON-MODE DC INPUT VOLTAGE	(V ⁺ +8 V) to (V ⁻ -0.5 V)	
INPUT-TERMINAL CURRENT	1 mA	
DEVICE DISSIPATION:		
WITHOUT HEAT SINK -		
UP TO 55°C	630 mW	
ABOVE 55°C	Derate linearly 6.67 mW/°C	
WITH HEAT SINK -		
Up to 55°C	1 W	
Above 55°C	Derate linearly 16.7 mW/°C	
TEMPERATURE RANGE:		
OPERATING (ALL TYPES)	-55 to + 125°C	
STORAGE (ALL TYPES)	-65 to +150°C	
OUTPUT SHORT-CIRCUIT DURATION*	INDEFINITE	
LEAD TEMPERATURE (DURING SOLDERING):		
AT DISTANCE 1/16 ± 1/32 INCH (1.59 ± 0.79 MM)		
FROM CASE FOR 10 SECONDS MAX.	+265°C	

* Short circuit may be applied to ground or to either supply.

TYPICAL ELECTRICAL CHARACTERISTICS FOR DESIGN GUIDANCE

At V⁺ = 5 V, V⁻ = 0 V, T_A = 25°C

CHARACTERISTIC		CA3140B (T,S)	CA3140A (T,S,E)	CA3140 (T,S,E)	UNITS
Input Offset Voltage	V _{IO}	0.8	2	5	mV
Input Offset Current	I _{IO}	0.1	0.1	0.1	pA
Input Current	I _I	2	2	2	pA
Input Resistance		1	1	1	TΩ
Large-Signal Voltage Gain (See Figs. 4, 18)	A _{OL}	100 k	100 k	100 k	V/V
		100	100	100	dB
Common-Mode Rejection Ratio,	CMRR	20	32	32	μV/V
		94	90	90	dB
Common-Mode Input-Voltage Range (See Fig. 20)	V _{ICR}	-0.5	-0.5	-0.5	V
		2.6	2.6	2.6	
Power-Supply Rejection Ratio	ΔV _{IO} /ΔV ⁺	32	100	100	μV/V
		90	80	80	dB
Maximum Output Voltage (See Figs. 13, 20)	V _{OM} ⁺	3	3	3	V
	V _{OM} ⁻	0.13	0.13	0.13	
Maximum Output Current:					mA
Source	I _{OM} ⁺	10	10	10	
Sink	I _{OM} ⁻	1	1	1	
Slew Rate (See Fig. 6)		7	7	7	V/μs
Gain-Bandwidth Product (See Fig. 5)	f _T	3.7	3.7	3.7	MHz
Supply Current (See Fig. 7)	I ⁺	1.6	1.6	1.6	mA
Device Dissipation	P _D	8	8	8	mW
Sink Current from Term. 8 to Term. 4 to Swing Output Low		200	200	200	μA

Linear Integrated Circuits

CA3140, CA3140A, CA3140B Types

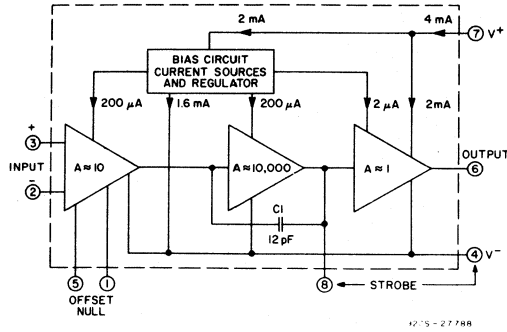
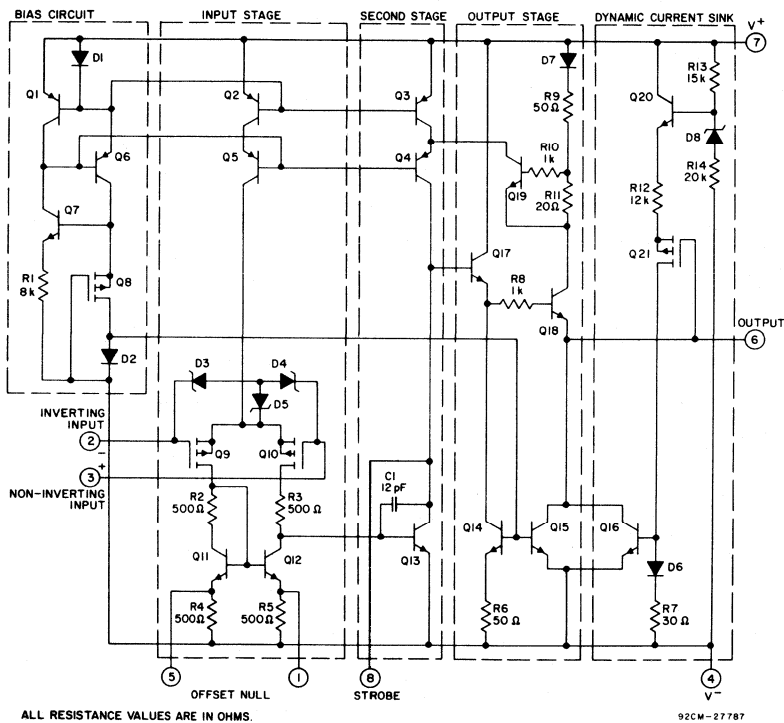


Fig.2 – Block diagram of CA3140 series.



ALL RESISTANCE VALUES ARE IN OHMS.

92CM-27787

Fig.3 – Schematic diagram of CA3140 series.

CIRCUIT DESCRIPTION

Fig.2 is a block diagram of the CA3140 Series PMOS Operational Amplifiers. The input terminals may be operated down to 0.5 V below the negative supply rail. Two class A amplifier stages provide the voltage gain, and a unique class AB amplifier stage provides the current gain necessary to drive low-impedance loads.

A biasing circuit provides control of cascaded constant-current flow circuits in the first and second stages. The CA3140 includes an on-

chip phase-compensating capacitor that is sufficient for the unity gain voltage-follower configuration.

Input Stages – The schematic circuit diagram of the CA3140 is shown in Fig.3. It consists of a differential-input stage using PMOS field-effect transistors (Q9, Q10) working into a mirror pair of bipolar transistors (Q11, Q12) functioning as load resistors together with resistors R2 through R5. The mirror-pair transistors also function as a differen-

CA3140, CA3140A, CA3140B Types

tial-to-single-ended converter to provide base-current drive to the second-stage bipolar transistor (Q13). Offset nulling, when desired, can be effected with a 10-k Ω potentiometer connected across terminals 1 and 5 and with its slider arm connected to terminal 4. Cascode-connected bipolar transistors Q2, Q5 are the constant-current source for the input stage. The base-biasing circuit for the constant-current source is described subsequently. The small diodes D3, D4, D5 provide gate-oxide protection against high-voltage transients, e.g., static electricity.

Second Stage — Most of the voltage gain in the CA3140 is provided by the second amplifier stage, consisting of bipolar transistor Q13 and its cascode-connected load resistance provided by bipolar transistors Q3, Q4. On-chip phase compensation, sufficient for a majority of the applications is provided by C1. Additional Miller-Effect compensation (roll-off) can be accomplished, when desired, by simply connecting a small capacitor between terminals 1 and 8. Terminal 8 is also used to strobe the output stage into quiescence. When terminal 8 is tied to the negative supply rail (terminal 4) by mechanical or electrical means, the output terminal 6 swings low, i.e., approximately to terminal 4 potential.

Output Stage — The CA3140 Series circuits employ a broadband output stage that can sink loads to the negative supply to complement the capability of the PMOS input stage when operating near the negative rail. Quiescent current in the emitter-follower cascade circuit (Q17, Q18) is established by transistors (Q14, Q15) whose base-currents are "mirrored" to current flowing through diode D2 in the bias circuit section. When the CA3140 is operating such that output terminal 6 is sourcing current, transistor Q18 functions as an emitter-follower to source current from the V+ bus (terminal 7), via D7, R9, and R11. Under these conditions, the collector potential of Q13 is sufficiently high to permit the necessary flow of base current to emitter follower Q17 which, in turn, drives Q18.

When the CA3140 is operating such that output terminal 6 is sinking current to the V- bus, transistor Q16 is the current-sinking

element. Transistor Q16 is mirror-connected to D6, R7, with current fed by way of Q21, R12, and Q20. Transistor Q20, in turn, is biased by current-flow through R13, zener D8, and R14. The dynamic current-sink is controlled by voltage-level sensing. For purposes of explanation, it is assumed that output terminal 6 is quiescently established at the potential mid-point between the V+ and V- supply rails. When output-current sinking-mode operation is required, the collector potential of transistor Q13 is driven below its quiescent level, thereby causing Q17, Q18 to decrease the output voltage at terminal 6. Thus, the gate terminal of PMOS transistor Q21 is displaced toward the V- bus, thereby reducing the channel resistance of Q21. As a consequence, there is an incremental increase in current flow through Q20, R12, Q21, D6; R7, and the base of Q16. As a result, Q16 sinks current from terminal 6 in direct response to the incremental change in output voltage caused by Q18. This sink current flows regardless of load; any excess current is internally supplied by the emitter-follower Q18. Short-circuit protection of the output circuit is provided by Q19, which is driven into conduction by the high voltage drop developed across R11 under output short-circuit conditions. Under these conditions, the collector of Q19 diverts current from Q4 so as to reduce the base-current drive from Q17, thereby limiting current flow in Q18 to the short-circuited load terminal.

Bias Circuit — Quiescent current in all stages (except the dynamic current sink) of the CA3140 is dependent upon bias current flow in R1. The function of the bias circuit is to establish and maintain constant-current flow through D1, Q6, Q8 and D2. D1 is a diode-connected transistor mirror-connected in parallel with the base-emitter junctions of Q1, Q2, and Q3. D1 may be considered as a current-sampling diode that senses the emitter current of Q6 and automatically adjusts the base current of Q6 (via Q1) to maintain a constant current through Q6, Q8, D2. The base-currents in Q2, Q3 are also determined by constant-current flow D1. Furthermore, current in diode-connected transistor D2 establishes the currents in transistors Q14 and Q15.

Linear Integrated Circuits

CA3140, CA3140A, CA3140B Types

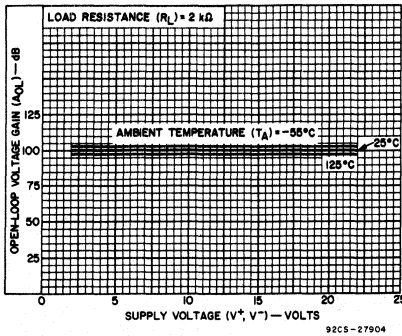


Fig. 4 — Open-loop voltage gain vs supply voltage and temperature.

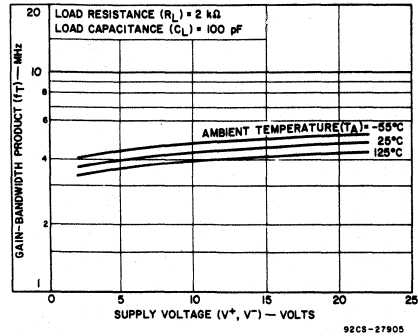


Fig. 5 — Gain-bandwidth product vs supply voltage and temperature.

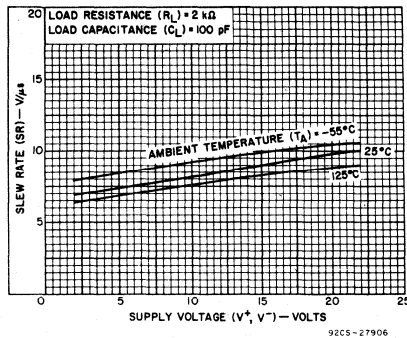


Fig. 6 — Slew rate vs supply voltage and temperature.

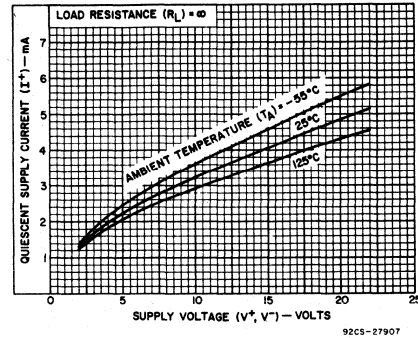


Fig. 7 — Quiescent supply current vs supply voltage and temperature.

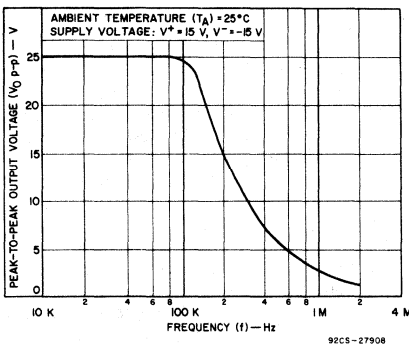


Fig. 8 — Maximum output voltage swing vs frequency.

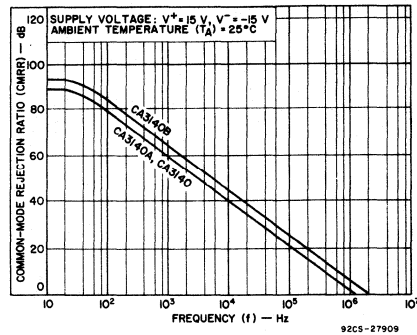


Fig. 9 — Common-mode rejection ratio vs frequency.

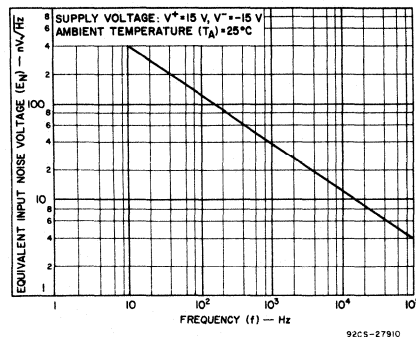


Fig. 10 — Equivalent input noise voltage vs frequency.

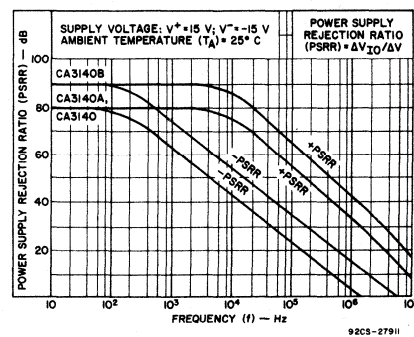


Fig. 11 — Power supply rejection ratio vs frequency.

CA3140, CA3140A, CA3140B Types

APPLICATIONS CONSIDERATIONS

Wide dynamic range of input and output characteristics with the most desirable high input-impedance characteristic is achieved in the CA3140 by the use of a unique design based upon the PMOS-Bipolar process. Input-common-mode voltage range and output-swing capabilities are complementary, allowing operation with the single supply down to four volts.

The wide dynamic range of these parameters also means that this device is suitable for many single-supply applications, such as, for example, where one input is driven below the potential of terminal 4 and the phase sense of the output signal must be maintained — a most important consideration in comparator applications.

OUTPUT CIRCUIT CONSIDERATIONS

Excellent interfacing with TTL circuitry is easily achieved with a single 6.2-volt zener diode connected to terminal 8 as shown in Fig.12. This connection assures that the maximum output signal swing will not go more positive than the zener voltage minus two base-to-emitter voltage drops within the CA3140. These voltages are independent of the operating supply voltage.

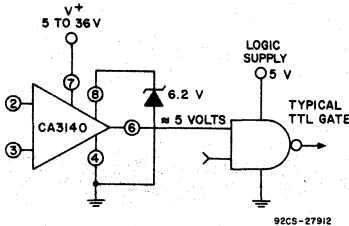


Fig.12 — Zener clamping diode connected to terminals 8 and 4 to limit CA3140 output swing to TTL levels.

Fig.13 shows output current-sinking capabilities of the CA3140 at various supply voltages. Output voltage swing to the negative supply rail permits this device to oper-

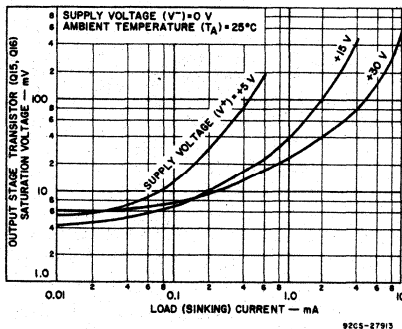


Fig.13 — Voltage across output transistors Q15 and Q16 vs load current.

ate both power transistors and thyristors directly without the need for level-shifting circuitry usually associated with the 741 series of operational amplifiers.

Fig.16 show some typical configurations. Note that a series resistor, R_L , is used in both cases to limit the drive available to the driven device. Moreover, it is recommended that a series diode and shunt diode be used at the thyristor input to prevent large negative transient surges that can appear at the gate of thyristors, from damaging the integrated circuit.

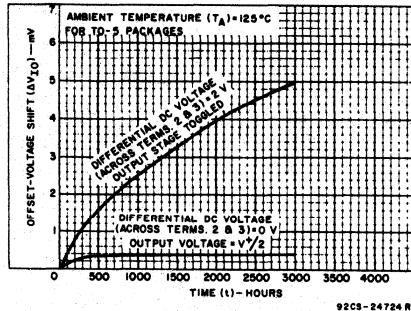


Fig.14 — Typical incremental offset-voltage shift vs operating life.

OFFSET-VOLTAGE NULLING

The input-offset voltage can be nulled by connecting a 10-k Ω potentiometer between terminals 1 and 5 and returning its wiper arm to terminal 4, see Fig.15a. This technique, however, gives more adjustment range than required and therefore, a considerable portion of the potentiometer rotation is not fully utilized. Typical values of series resistors that may be placed at either end of the potentiometer, see Fig.15b, to optimize its utilization range are given in the table "Typical Electrical Characteristics" shown in this bulletin.

An alternate system is shown in Fig.15c. This circuit uses only one additional resistor of approximately the value shown in the table. For potentiometers, in which the resistance does not drop to zero ohms at either end of rotation, a value of resistance 10% lower than the values shown in the table should be used.

LOW-VOLTAGE OPERATION

Operation at total supply voltages as low as 4 volts is possible with the CA3140. A current regulator based upon the PMOS threshold voltage maintains reasonable constant operating current and hence consistent performance down to these lower voltages.

The low-voltage limitation occurs when the upper extreme of the input common-mode voltage range extends down to the voltage at terminal 4. This limit is reached at a total

CA3140, CA3140A, CA3140B Types

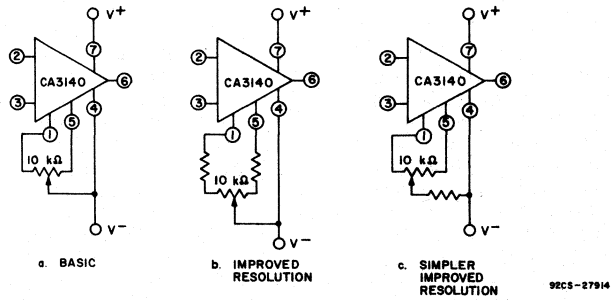


Fig. 15 — Three offset-voltage nulling methods.

supply voltage just below 4 volts. The output voltage range also begins to extend down to the negative supply rail, but is slightly higher than that of the input. Fig. 20 shows these characteristics and shows that with 2-volt dual supplies, the lower extreme of the input common-mode voltage range is below ground potential.

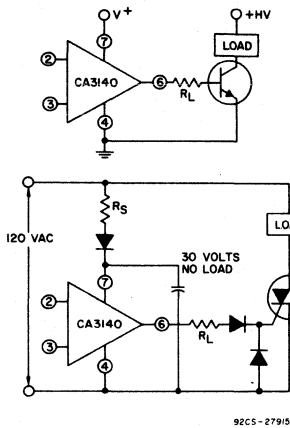


Fig. 16 — Methods of utilizing the $V_{CE(sat)}$ sinking-current capability of the CA3140 series.

BANDWIDTH AND SLEW RATE

For those cases where bandwidth reduction is desired, for example, broadband noise reduction, an external capacitor connected between terminals 1 and 8 can reduce the open-loop -3 dB bandwidth. The slew rate will, however, also be proportionally reduced by using this additional capacitor. Thus, a 20% reduction in bandwidth by this technique will also reduce the slew rate by about 20%.

Fig. 17 shows the typical settling time required to reach 1 mV or 10 mV of the final value for various levels of large signal inputs for the voltage-follower and inverting unity-gain amplifiers. The exceptionally fast settling time characteristics are largely due to the high combination of high gain and wide bandwidth of the CA3140; as shown in Fig. 18.

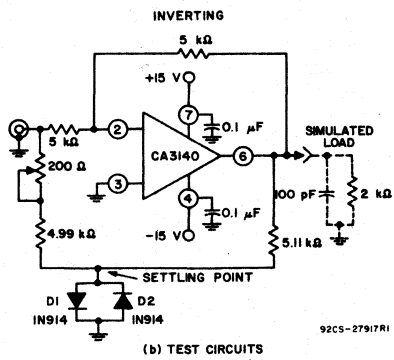
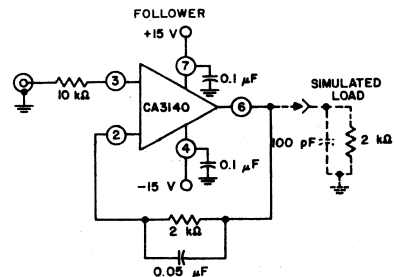
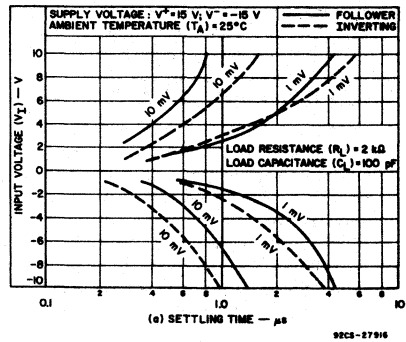


Fig. 17 — Input voltage vs settling time.

INPUT CIRCUIT CONSIDERATIONS

As mentioned previously, the amplifier inputs can be driven below the terminal 4 potential, but a series current-limiting res-

CA3140, CA3140A, CA3140B Types

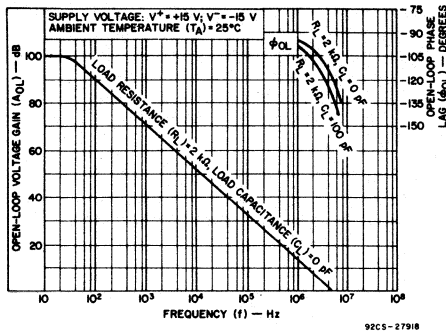


Fig. 18 - Open-loop voltage gain and phase lag vs frequency.

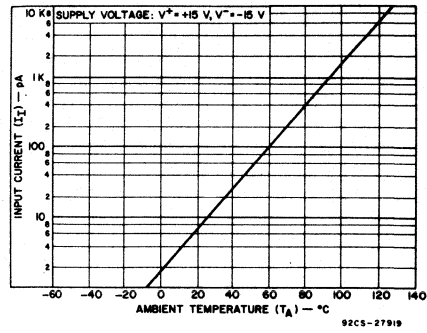


Fig. 19 - Input current vs ambient temperature.

sistor is recommended to limit the maximum input terminal current to less than 1 mA to prevent damage to the input protection circuitry.

Moreover, some current-limiting resistance should be provided between the inverting input and the output when the CA3140 is used as a unity-gain voltage follower. This resistance prevents the possibility of extremely large input-signal transients from forcing a signal through the input-protection network and directly driving the internal constant-current source which could result in positive feedback via the output terminal. A 3.9-kΩ resistor is sufficient.

The typical input current is in the order of 10 pA when the inputs are centered at nominal device dissipation. As the output supplies load current, device dissipation will increase, raising the chip temperature and resulting in increased input current. Fig.19 shows typical input-terminal current versus ambient temperature for the CA3140.

It is well known that MOS/FET devices can exhibit slight changes in characteristics (for example, small changes in input offset voltage) due to the application of large differential input voltages that are sustained over long periods at elevated temperatures.

Both applied voltage and temperature accelerate these changes. The process is reversible and offset voltage shifts of the opposite polarity reverse the offset. Fig.14 shows the typical offset voltage change as a function of various stress voltages at the maximum rating of 125°C (for TO-5); at lower temperatures (TO-5 and plastic), for example, at 85°C, this change in voltage is considerably less. In typical linear applications, where the differential voltage is small and symmetrical, these incremental changes are of about the same magnitude as those encountered in an operational amplifier employing a bipolar a transistor input stage.

SUPER SWEEP FUNCTION GENERATOR

A function generator having a wide tuning range is shown in Fig.21. The 1,000,000/

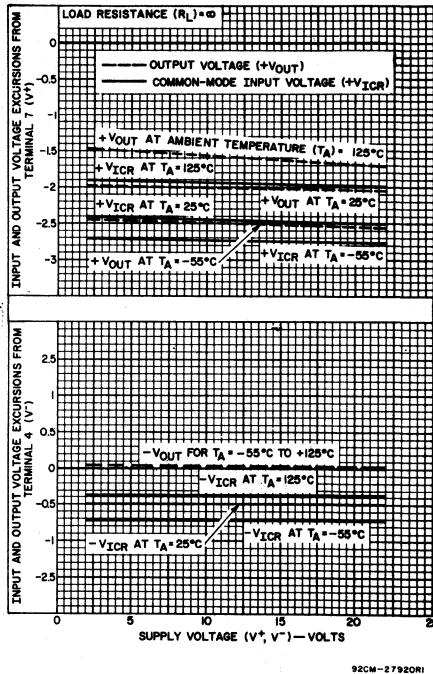


Fig.20 - Output-voltage-swing capability and common-mode input-voltage range vs supply voltage and temperature.

adjustment range is accomplished by a single variable potentiometer or by an auxiliary sweeping signal. The CA3140 functions as a non-inverting read-out amplifier of the triangular signal developed across the integrating capacitor network connected to the output of the CA3080A current source.

Buffered triangular output signals are then applied to a second CA3080 functioning as a high-speed hysteresis switch. Output from the switch is returned directly back to the

CA3140, CA3140A, CA3140B Types

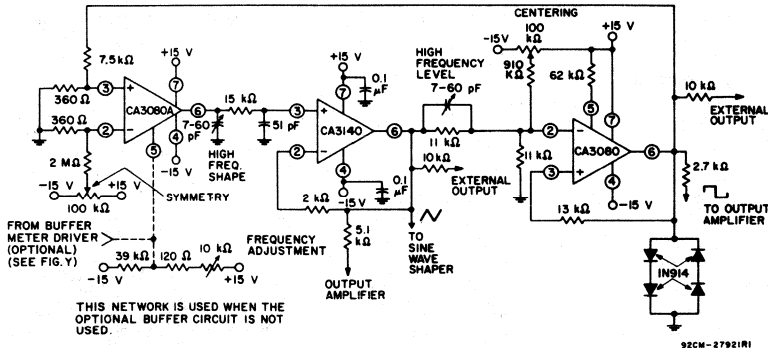
input of the CA3080A current source, thereby, completing the positive feedback loop.

The triangular output level is determined by the four 1N914 level-limiting diodes of the second CA3080 and the resistor-divider network connected to terminal No.2 (input) of the CA3080. These diodes establish the input trip level to this switching stage and, therefore, indirectly determine the amplitude of the output triangle.

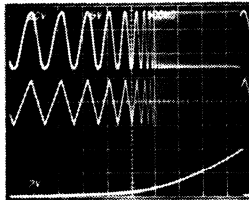
Compensation for propagation delays around the entire loop is provided by one adjust-

ment on the input of the CA3080. This adjustment, which provides for a constant generator amplitude output, is most easily made while the generator is sweeping. High-frequency ramp linearity is adjusted by the single 7-to-60 pF capacitor in the output of the CA3080A.

It must be emphasized that only the CA3080A is characterized for maximum output linearity in the current-generator function.



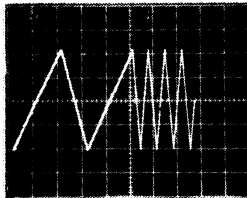
(a) Circuit



TOP TRACE: OUTPUT AT JUNCTION OF 2.7 Ω AND 51 Ω RESISTORS 5V/DIV AND 500 ms/DIV
 CENTER TRACE: EXTERNAL OUTPUT OF TRIANGULAR FUNCTION GENERATOR 2V/DIV AND 500 ms/DIV
 BOTTOM TRACE: OUTPUT OF "LOG" GENERATOR 10V/DIV AND 500 ms/DIV

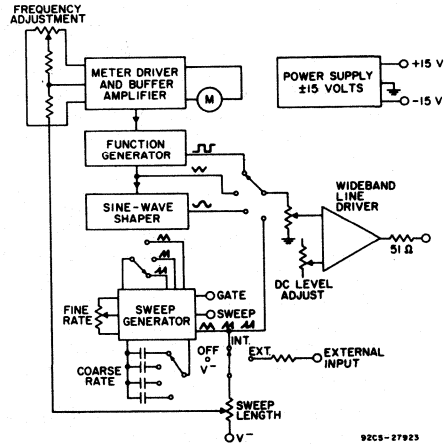
92CS-27922

(b1) Function generator sweeping



92CS-27937

(b2) Function generator with fixed frequencies



(c) Interconnections

1V/DIV and 1 sec/DIV

Three tone test signals, highest frequency ≥ 0.5 MHz. Note the slight asymmetry at the three-second/cycle signal. This asymmetry is due to slightly different positive and negative integration from the CA3080A and from the pc board and component leakages at the 100-pA level.

Fig.21 - Function generator.

CA3140, CA3140A, CA3140B Types

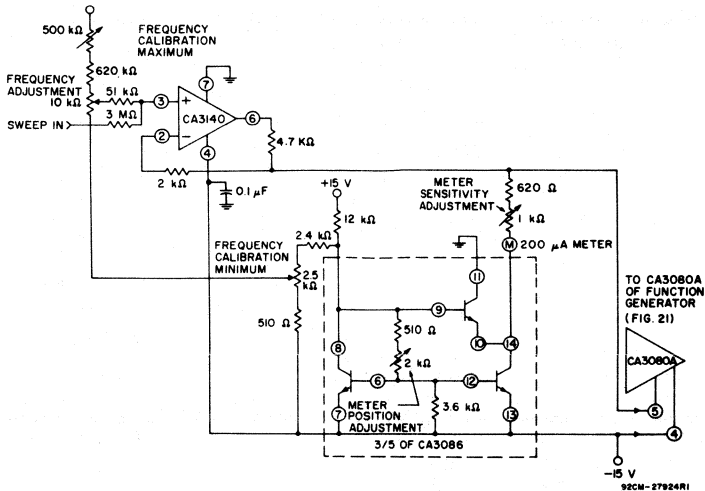


Fig. 22 — Meter driver and buffer amplifier.

METER DRIVER AND BUFFER AMPLIFIER

Fig. 22 shows the CA3140 connected as a meter driver and buffer amplifier. Low driving impedance is required of the CA3080A current source to assure smooth operation of the Frequency Adjustment Control. This low-driving impedance requirement is easily met by using a CA3140 connected as a voltage follower. Moreover, a meter may be placed across the input to the CA3080A to give a logarithmic analog indication of the function generators frequency.

Analog frequency readout is readily accomplished by the means described above because the output current of the CA3080A varies approximately one decade for each 60-mV change in the applied voltage, V_{ABC} (voltage between terminals 5 and 4 of the CA3080A of the function generator). Therefore, six decades represent 360-mV change in V_{ABC} .

Now, only the reference voltage must be established to set the lower limit on the meter. The three remaining transistors from the CA3086 Array used in the sweep generator are used for this reference voltage. In addition, this reference generator arrangement tends to track ambient temperature variations, and thus compensates for the effects of the normal negative temperature coefficient of the CA3080A V_{ABC} terminal voltage.

Another output voltage from the reference generator is used to insure temperature tracking of the lower end of the Frequency Adjustment Potentiometer. A large series resistance simulates a current source, assuring similar temperature coefficients at both ends of the Frequency Adjustment Control.

To calibrate this circuit, set the Frequency Adjustment Potentiometer at its low end. Then adjust the Minimum Frequency Calibration Control for the lowest frequency. To establish the upper frequency limit, set the Frequency Adjustment Potentiometer to its upper end and then adjust the Maximum Frequency Calibration Control for the maximum frequency. Because there is interaction among these controls, repetition of the adjustment procedure may be necessary.

Two adjustments are used for the meter. The meter sensitivity control sets the meter-scale width of each decade, while the meter position control adjusts the pointer on the scale with negligible effect on the sensitivity adjustment. Thus, the meter sensitivity adjustment control calibrates the meter so that it deflects 1/6 of full scale for each decade change in frequency.

SINE-WAVE SHAPER

The circuit shown in Fig. 23 uses a CA3140 as a voltage follower in combination with diodes from the CA3019 Array to convert the triangular signal from the function generator to a sine-wave output signal having typically less than 2% THD. The basic zero-crossing slope is established by the 10-kΩ potentiometer connected between terminals 2 and 6 of the CA3140 and the 9.1-kΩ resistor and 10-kΩ potentiometer from terminal 2 to ground. Two break points are established by diodes D_1 through D_4 . Positive feedback via D_5 and D_6 establishes the zero slope at the maximum and minimum levels of the sine wave. This technique is necessary because the voltage-follower configuration approaches unity gain rather than the zero gain required to shape the sine wave at the two extremes.

CA3140, CA3140A, CA3140B Types

This circuit can be adjusted most easily with a distortion analyzer, but a good first approximation can be made by comparing the output signal with that of a sine-wave generator. The initial slope is adjusted with the potentiometer R₁, followed by an adjustment of R₂. The final slope is established by adjusting R₃, thereby adding additional segments that are contributed by these diodes. Because there is some interaction among these controls, repetition of the adjustment procedure may be necessary.

SWEEPING GENERATOR

Fig. 24 shows a sweeping generator. Three CA3140's are used in this circuit. One CA3140 is used as an integrator, a second device is used as a hysteresis switch that determines the starting and stopping points of the sweep. A third CA3140 is used as a logarithmic shaping network for the log function. Rates and slopes, as well as sawtooth, triangle, and logarithmic sweeps are generated by this circuit.

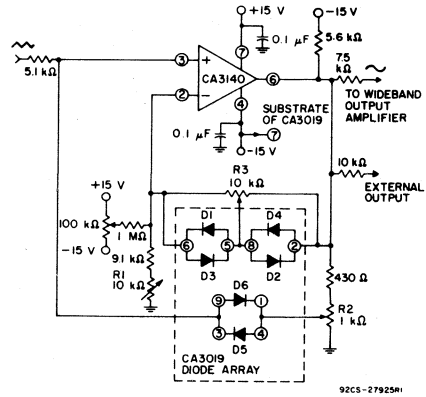


Fig. 23 — Sine-wave shaper.

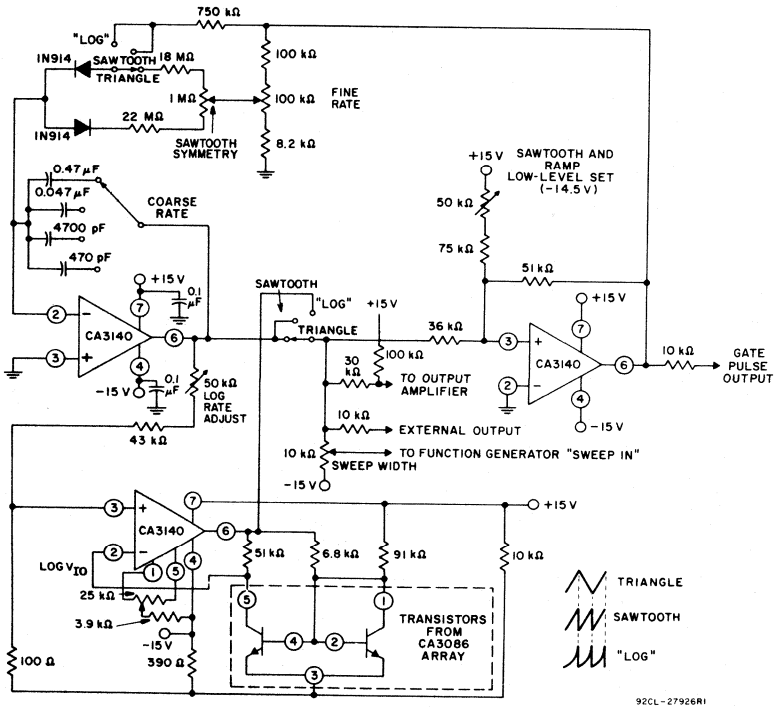


Fig. 24 — Sweeping generator.

CA3140, CA3140A, CA3140B Types

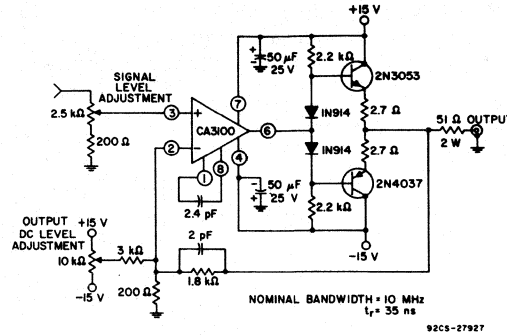


Fig. 25 — Wideband output amplifier.

WIDEBAND OUTPUT AMPLIFIER

Fig. 25 shows a high-slew-rate, wideband amplifier suitable for use as a 50-ohm transmission-line driver. This circuit, when used in conjunction with the function generator and sine-wave shaper circuits shown in Figs. 21 and 23 provides 18 volts peak-to-peak output open-circuited, or 9 volts peak-to-peak output when terminated in 50 ohms. The slew rate required of this amplifier is 28 volts/μs (18 volts peak-to-peak x π x 0.5 MHz).

POWER SUPPLIES

High input-impedance, common-mode capability down to the negative supply and high output-drive current capability are key factors in the design of wide-range output-voltage supplies that use a single input voltage to provide a regulated output voltage that can be adjusted from essentially 0 to 24 volts. Unlike many regulator systems using comparators having a bipolar transistor-input stage, a high-impedance reference-voltage divider from a single supply can be used in connection with the CA3140 (see Fig. 26).

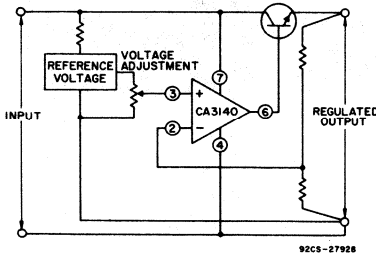


Fig. 26 — Basic single-supply voltage regulator showing voltage-follower configuration.

Essentially, the regulators, shown in Figs. 27 and 28, are connected as non-inverting power operational amplifiers with a gain of 3.2. An 8-volt reference input yields a maximum output voltage slightly greater than 25 volts. As a voltage follower, when the reference input goes to 0 volts the output will be 0 volts. Because the offset voltage is also multiplied by the 3.2 gain factor, a potentiometer is needed to null the offset voltage.

Series pass transistors with high ICBO levels will also prevent the output voltage from reaching zero because there is a finite voltage drop (V_{CEsat}) across the output of the CA3140 (see Fig.13). This saturation voltage level may indeed set the lowest voltage obtainable.

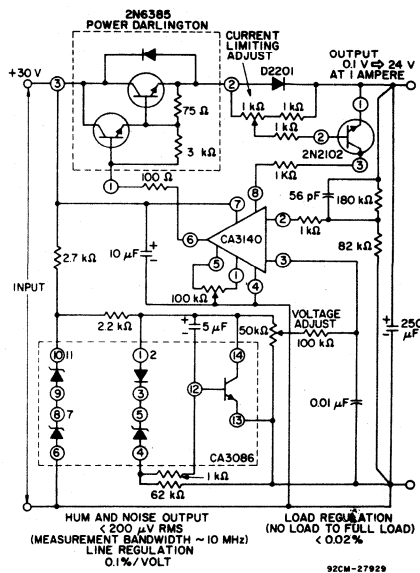


Fig. 27 — Regulated power supply.

Linear Integrated Circuits

CA3140, CA3140A, CA3140B Types

The high impedance presented by terminal 8 is advantageous in effecting current limiting. Thus, only a small signal transistor is required for the current-limit sensing amplifier. Resistive decoupling is provided for this transistor to minimize damage to it or the CA3140 in the event of unusual input or output transients on the supply-rail.

Figs. 27 and 28, show circuits in which a D2201 high-speed diode is used for the current sensor. This diode was chosen for its slightly higher forward-voltage drop characteristic thus giving greater sensitivity. It must be emphasized that heat sinking of this diode is essential to minimize variation of the current trip point due to internal heating of the diode. That is, 1 ampere at 1 volt forward drop represents one watt which can result in significant regenerative changes in the current trip point as the diode temperature rises. Placing the small-signal reference amplifier in the proximity of the current-sensing diode also helps minimize the variability in the trip level due to the negative temperature coefficient of the diode. In spite of those limitations, the current limiting point can easily be adjusted over the range from 10 mA to 1 ampere with a single adjustment potentiometer. If the temperature stability of the current-limiting system is a serious consideration, the more usual current-sampling resistor-type of circuitry should be employed.

A power Darlington transistor (in a heat sink TO-3 case), is used as the series-pass element for the conventional current-limiting system, Fig. 27, because high-power Darlington dissipation will be encountered at low output voltage and high currents.

A small heat-sink VERSAWATT transistor is used as the series-pass element in the foldback current system, Fig. 28, since dissipation levels will only approach 10 watts. In this system, the D2201 diode is used for current sampling. Foldback is provided by the 3 kΩ and 100 kΩ divider network connected to the base of the current-sensing transistor.

Both regulators, Figs. 27 and 28, provide better than 0.02% load regulation. Because there is constant loop gain at all voltage settings, the regulation also remains constant. Line regulation is 0.1% per volt. Hum and noise voltage is less than 200 μV as read with a meter having a 10-MHz bandwidth.

Fig. 31 (a) shows the turn ON and turn OFF characteristics of both regulators. The slow turn-on rise is due to the slow rate of rise of the reference voltage. Fig. 29 (b) shows the transient response of the regulator with the switching of a 20-Ω load at 20 volts output.

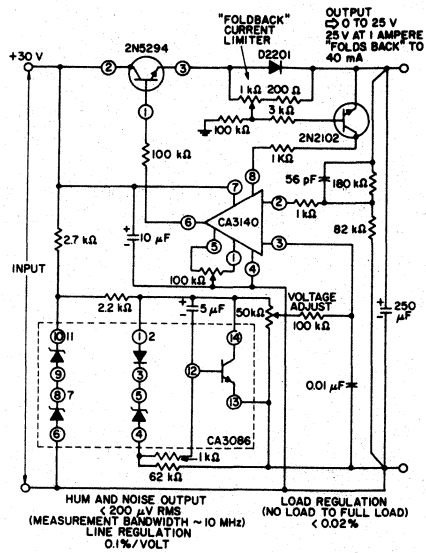
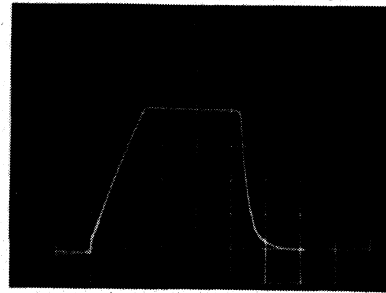
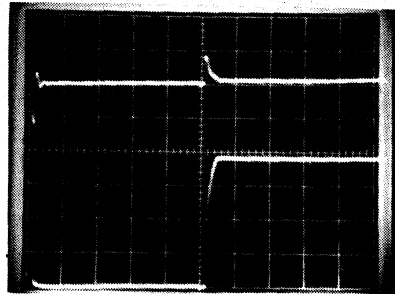


Fig. 28 - Regulated power supply with "foldback" current limiting.



SUPPLY TURN-ON AND TURN-OFF CHARACTERISTICS (5 VOLTS / DIV AND -1 s / DIV.)

92CS-27882



TRANSIENT RESPONSE
TOP TRACE: OUTPUT VOLTAGE (200 mV/DIV AND 5 μs/DIV)
BOTTOM TRACE: COLLECTOR OF LOAD SWITCHING TRANSISTOR, LOAD = 1 AMPERE (5 VOLTS/DIV AND 5 μs/DIV)

92CS-27881

Fig. 29 - Waveforms of dynamic characteristics of power supply currents shown in Figs. 29 and 30.

CA3140, CA3140A, CA3140B Types

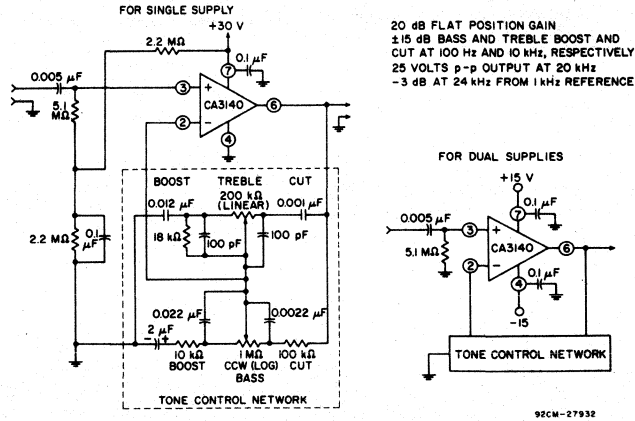


Fig. 30 - Tone control circuit using CA3130 series (20-dB midband gain).

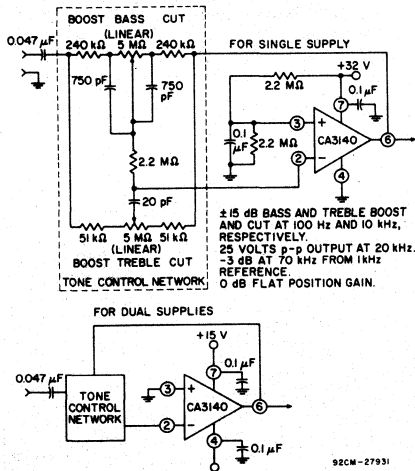


Fig. 31 - Baxandall tone control circuit using CA3140 series.

TONE CONTROL CIRCUITS

High-slew-rate, wide-bandwidth, high-output voltage capability and high input impedance are all characteristics required of tone-control amplifiers. Two tone control circuits that exploit these characteristics of the CA3140 are shown in Figs. 30 and 31.

The first circuit, shown in Fig. 31, is the Baxandall tone-control circuit which provides unity gain at midband and uses standard linear potentiometers. The high input impedance of the CA3140 makes possible the use of low-cost, low-value, small-size capacitors, as well as reduced load of the driving stage.

Bass treble boost and cut are \pm 15 dB at 100 Hz and 10 kHz, respectively. Full peak-to-peak output is available up to at least 20 kHz due to the high slew rate of the CA3140. The amplifier gain is -3 dB down from its "flat" position at 70 kHz.

Fig. 30 shows another tone-control circuit with similar boost and cut specifications. The wideband gain of this circuit is equal to the ultimate boost or cut plus one, which in this case is a gain of eleven. For 20-dB boost and cut, the input loading of this circuit is essentially equal to the value of the resistance from terminal No.3 to ground. A detailed analysis of this circuit is given in "An IC Operational Transconductance Amplifier (OTA) With Power Capability" by L. Kaplan and H. Wittlinger, IEEE Transactions on Broadcast and Television Receivers, Vol. BTR-18, No.3, August, 1972.

WIEN BRIDGE OSCILLATOR

Another application of the CA3140 that makes excellent use of its high input-impedance, high-slew-rate, and high-voltage qualities is the Wien Bridge sine-wave oscillator. A basic Wien Bridge oscillator is shown in Fig. 32. When $R_1 = R_2 = R$ and $C_1 = C_2 = C$, the frequency equation reduces to the familiar $f = 1/2\pi RC$ and the gain required for oscillation, A_{OSC} is equal to 3. Note that if C_2 is increased by a factor of four and R_2 is reduced by a factor of four, the gain required for oscillation becomes 1.5, thus per-

CA3140, CA3140A, CA3140B Types

mitting a potentially higher operating frequency closer to the gain-bandwidth product of the CA3140.

Oscillator stabilization takes on many forms. It must be precisely set, otherwise the amplitude will either diminish or reach some form of limiting with high levels of distortion. The element, R_S , is commonly replaced with some variable resistance element. Thus, through some control means, the value of R_S is adjusted to maintain constant oscillator output. A FET channel resistance, a thermistor, a lamp bulb, or other device whose resistance is made to increase as the output amplitude is increased are a few of the elements often utilized.

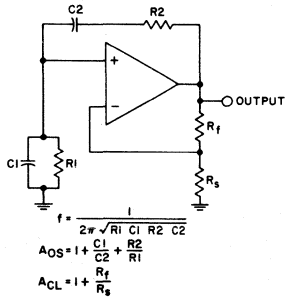


Fig. 32 — Basic Wien bridge oscillator circuit using an operational amplifier.

Fig. 33 shows another means of stabilizing the oscillator with a zener diode shunting the feedback resistor (R_f of Fig. 32). As the output signal amplitude increases, the zener diode impedance decreases resulting in more feedback with consequent reduction in gain; thus stabilizing the amplitude of the output signal. Furthermore, this combination of a monolithic zener diode and bridge rectifier circuit tends to provide a zero temperature coefficient for this regulating system. Because this bridge rectifier system has no time constant, i.e., thermal time constant for the lamp bulb, and RC time constant for filters often used in detector networks, there is no lower frequency limit. For example, with 1- μ F polycarbonate capacitors and 22 M Ω for the frequency determining network, the operating frequency is 0.007 Hz.

As the frequency is increased, the output amplitude must be reduced to prevent the output signal from becoming slew-rate limited. An output frequency of 180 kHz will reach a slew rate of approximately 9 volts/ μ s when its amplitude is 16 volts peak-to-peak.

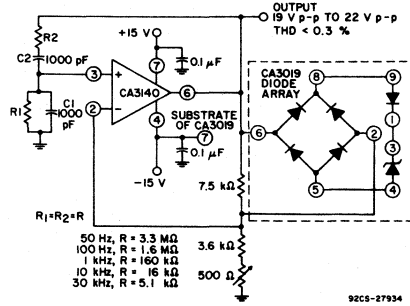


Fig. 33 — Wien bridge oscillator circuit using CA3140 series.

SIMPLE SAMPLE-AND-HOLD SYSTEM

Fig. 34 shows a very simple sample-and-hold system using the CA3140 as the readout amplifier for the storage capacitor. The CA3080A serves as both input buffer amplifier and low feed-through transmission switch.* System offset nulling is accom-

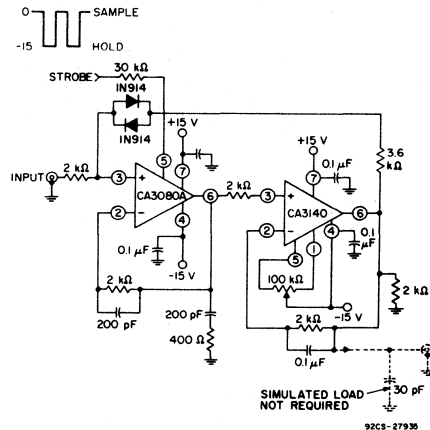


Fig. 34 — Sample-and hold circuit.

plished with the CA3140 via its offset nulling terminals. A typical simulated load of 2 k Ω and 30 pF is shown in the schematic.

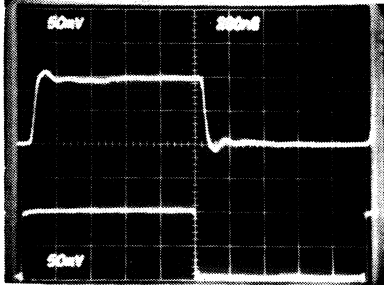
In this circuit, the storage compensation capacitance (C_1) is only 200 pF. Larger value capacitors provide longer "hold" periods but with slower slew rates. The slew rate

$$\frac{dv}{dt} = \frac{i}{c} = 0.5 \text{ mA}/200 \text{ pF} = 2.5 \text{ V}/\mu\text{s}.$$

* ICAN-6668 "Applications of the CA3080 and CA3080A High-Performance Operational Transconductance Amplifiers".

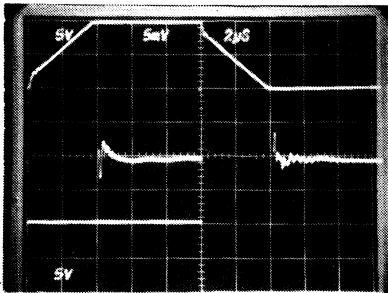
CA3140, CA3140A, CA3140B Types

Pulse "droop" during the hold interval is $170 \text{ pA}/200 \text{ pF}$ which is $= 0.85 \text{ } \mu\text{V}/\mu\text{s}$; (i.e., $170 \text{ pA}/200 \text{ pF}$). In this case, 170 pA represents the typical leakage current of the CA3080A when strobed off. If C_1 were increased to 2000 pF , the "hold-droop" rate will decrease to $0.085 \text{ } \mu\text{V}/\mu\text{s}$, but the slew rate would decrease to $0.25 \text{ V}/\mu\text{s}$. The parallel diode network connected between terminal



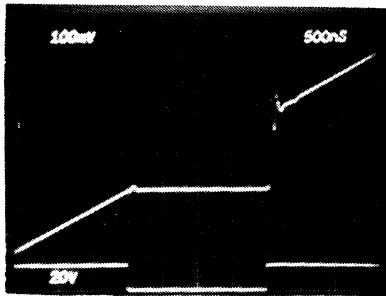
TOP TRACE: OUTPUT
(50 mV/DIV. AND 200 ns/DIV.)
BOTTOM TRACE: INPUT
(50 mV/DIV. AND 200 ns/DIV.)

92CS-27883



LARGE-SIGNAL RESPONSE AND
SETTLING TIME
TOP TRACE: OUTPUT SIGNAL
(5 V/DIV. AND 2 μs /DIV.)
BOTTOM TRACE: INPUT SIGNAL
(5 V/DIV. AND 2 μs /DIV.)
CENTER TRACE: DIFFERENCE OF INPUT AND OUTPUT
SIGNALS THROUGH TEKTRONIX
AMPLIFIER 7A13
(5 mV/DIV. AND 2 μs /DIV.)

92CS-27884



SAMPLING RESPONSE
TOP TRACE: SYSTEM OUTPUT
(100 mV/DIV. AND 500 ns/DIV.)
BOTTOM TRACE: SAMPLING SIGNAL
(20 V/DIV. AND 500 ns/DIV.)

92CS-27885

Fig. 35 — Sample-and hold system dynamic characteristics waveforms.

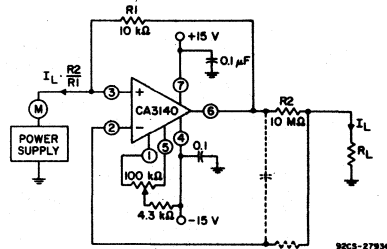
3 of the CA3080A and terminal 6 of the CA3140 prevents large input-signal feed-through across the input terminals of the CA3080A to the 200 pF storage capacitor when the CA3080A is strobed off. Fig. 35 shows dynamic characteristic waveforms of this sample-and-hold system.

CURRENT AMPLIFIER

The low input-terminal current needed to drive the CA3140 makes it ideal for use in current-amplifier applications such as the one shown in Fig. 36. In this circuit, low current is supplied at the input potential as the power supply to load resistor R_L . This load current is increased by the multiplication factor R_2/R_1 , when the load current is monitored by the power supply meter M. Thus, if the load current is 100 nA , with values shown, the load current presented to the supply will be $100 \text{ } \mu\text{A}$; a much easier current to measure in many systems.

Note that the input and output voltages are transferred at the same potential and only the output current is multiplied by the scale factor.

The dotted components show a method of decoupling the circuit from the effects of high output-load capacitance and the potential oscillation in this situation. Essentially, the necessary high-frequency feedback is provided by the capacitor with the dotted series resistor providing load decoupling.



92CS-27936

Fig. 36 — Basic current amplifier for low-current measurement systems.

Fig. 37 shows a single-supply, absolute-value, ideal full-wave rectifier with associated waveforms. During positive excursions, the input signal is fed through the feedback network directly to the output. Simultaneously, the positive excursion of the input signal also drives the output terminal (No.6) of the inverting amplifier in a negative-going excursion such that the 1N914 diode effectively disconnects the amplifier from the signal path. During a negative-going excursion of the input signal, the CA3140 functions as a normal inverting amplifier with a gain equal to $-R_2/R_1$. When the equality of the two equations shown in Fig. 37 is satisfied, the full-wave output is symmetrical.

- "Operational Amplifiers Design and Applications", J. G. Graeme, McGraw-Hill Book Company, page 308 — "Negative Imittance Converter Circuits".

Linear Integrated Circuits

CA3140, CA3140A, CA3140B Types

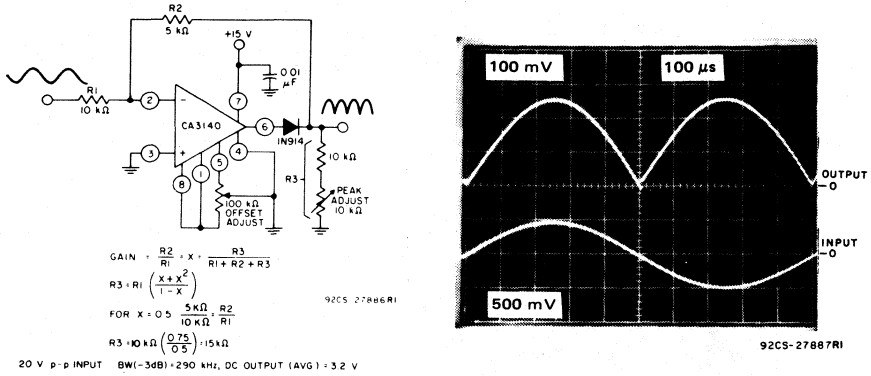


Fig. 37 — Single-supply, absolute-value, ideal full-wave rectifier with associated waveforms.

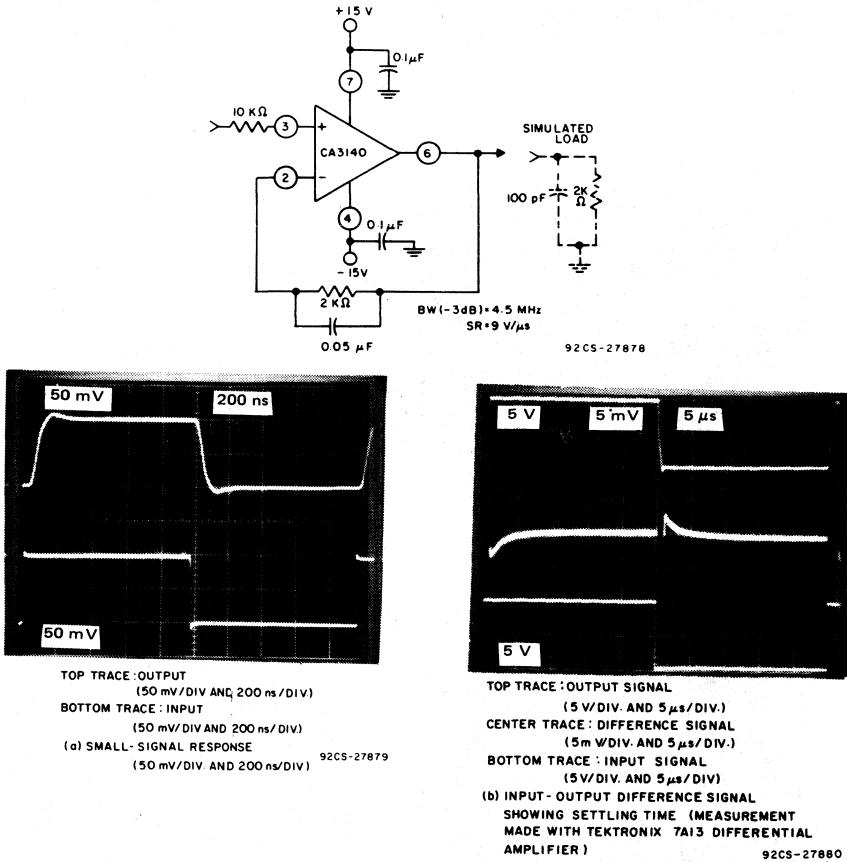


Fig. 38 — Split-supply voltage-follower test circuit and associated waveforms.

CA3140, CA3140A, CA3140B Types

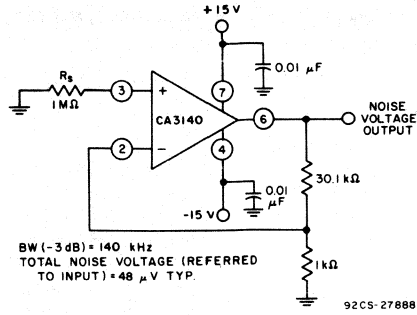
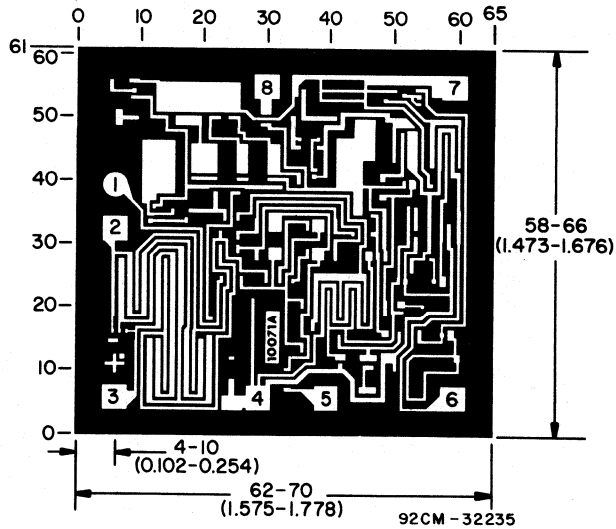


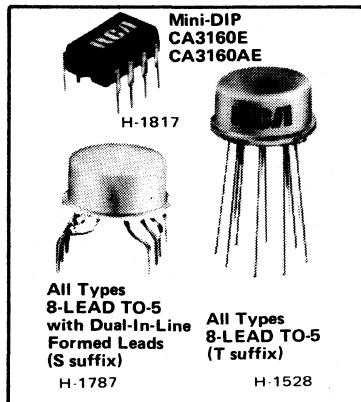
Fig. 39 — Test circuit amplifier (30-dB gain) used for wideband noise measurement.



The photographs and dimensions represent a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch).

CA3160, CA3160A, CA3160B Types



BiMOS Operational Amplifiers

With MOS/FET Input, COS/MOS Output

FEATURES:

- Similar to CA3130 but has internal compensation
 - MOS/FET input stage provides:
 - very high $Z_I = 1.5 T\Omega$ ($1.5 \times 10^{12}\Omega$) typ.
 - very low $I_I = 5$ pA typ. at 15-V operation
 - 2 pA typ. at 5-V operation
 - Common-mode input-voltage range includes negative supply rail; input terminals can be swung 0.5 V below negative supply rail
 - COS/MOS output stage permits signal swing to either (or both) supply rails
- } Ideal for single-supply applications

The RCA-CA3160T, CA3160S, CA3160E; CA3160AT, CA3160AS, CA3160AE; and CA3160BT, CA3160BS are integrated-circuit operational amplifiers that combine the advantages of both COS/MOS and bipolar transistors on a monolithic chip. The CA3160 series circuits are frequency-compensated versions of the popular CA3130 series.

Gate-protected p-channel MOS/FET (PMOS) transistors are used in the input circuit to provide very-high-input impedance, very-low-input current, and exceptional speed performance. The use of PMOS field-effect transistors in the input stage results in common-mode input-voltage capability down to 0.5 volt below the negative-supply terminal, an important attribute in single-supply applications.

A complementary-symmetry MOS (COS/MOS) transistor-pair, capable of swinging the output voltage to within 10 millivolts of either supply-voltage terminal (at very high values of load impedance), is employed as the output circuit.

The CA3160 Series circuits operate at supply voltages ranging from 5 to 16 volts, or +2.5 to +8 volts when using split supplies, and have terminals for adjustment of offset voltage for applications requiring offset-null capability. Terminal provisions are also made to permit strobing of the output stage.

The CA3160 series is supplied in standard 8-lead TO-5 style packages (T suffix) and 8-lead dual-in-line formed-lead TO-5 style "DIL-CAN" packages (S suffix). The CA3160 is available in chip form (H suffix).

- Low V_{IQ} : 2 mV max. (CA3160B)
- Wide BW: 4 MHz typ. (unity-gain crossover)
- High SR: 10 V/ μ s typ. (unity-gain follower)
- High output current (I_O): 20 mA typ.
- High A_{OL} : 320,000 (110 dB) typ.
- Internal phase compensation for unity gain (With terminal access for supplementary external phase compensation network if desired)

APPLICATIONS:

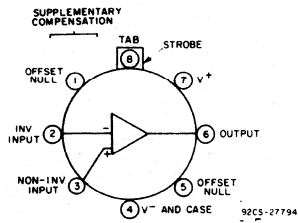
- Ground-referenced single-supply amplifiers
- Fast sample-hold amplifiers
- Long-duration timers/monostables
- Ideal interface with digital COS/MOS
- High-input-impedance wideband amplifiers
- Voltage followers (e.g., follower for single-supply D/A converter)
- Wien-Bridge oscillators
- Voltage-controlled oscillators
- Photo-diode sensor amplifiers

The CA3160A and CA3160 are also available in the 8-lead dual-in-line plastic package (Mini-DIP-E suffix). All types operate over the full military-temperature range of -55°C to $+125^\circ\text{C}$. The CA3160B is intended for applications requiring premium-grade specifications. The CA3160A offers superior input characteristics over those of the CA3160.

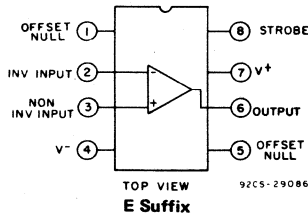
CA3160, CA3160A, CA3160B Types

ELECTRICAL CHARACTERISTICS at $T_A=25^\circ\text{C}$, $V^+=15\text{ V}$, $V^- = 0\text{ V}$ (Unless otherwise specified)

CHARACTERISTIC	LIMITS									Units		
	CA3160B (T, S)			CA3160A (T, S, E)			CA3160 (T, S, E)					
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.			
Input Offset Voltage, $ V_{IO} $, $V^\pm=\pm 7.5\text{ V}$	-	0.8	2	-	2	5	-	6	15	mV		
Input Offset Current, $ I_{IO} $, $V^\pm=\pm 7.5\text{ V}$	-	0.5	10	-	0.5	20	-	0.5	30	μA		
Input Current, I_I , $V^\pm=\pm 7.5\text{ V}$	-	5	20	-	5	30	-	5	50	μA		
Large-Signal Voltage Gain, A_{OL} $V_O=10\text{ V}_{p-p}$, $R_L=2\text{ k}\Omega$	100 k	320 k	-	50 k	320 k	-	50 k	320 k	-	V/V		
	100	110	-	94	110	-	94	110	-	dB		
Common-Mode Rejection Ratio, CMRR	86	100	-	80	95	-	70	90	-	dB		
Common-Mode Input-Voltage Range, V_{ICR}	0	-0.5 to 12	10	0	-0.5 to 12	10	0	-0.5 to 12	10	V		
Power-Supply Rejection Ratio, $\Delta V_{IO}/\Delta V^\pm$, $V^\pm=\pm 7.5\text{ V}$	-	32	100	-	32	150	-	32	320	$\mu\text{V}/\text{V}$		
Maximum Output Voltage:												
	At $R_L=2\text{ k}\Omega$	V_{OM}^+	12	13.3	-	12	13.3	-	12	13.3	-	V
		V_{OM}^-	-	0.002	0.01	-	0.002	0.01	-	0.002	0.01	
	At $R_L=\infty$	V_{OM}^+	14.99	15	-	14.99	15	-	14.99	15	-	
V_{OM}^-		-	0	0.01	-	0	0.01	-	0	0.01		
Maximum Output Current:												
	I_{OM}^+ (Source) @ $V_O=0\text{ V}$	12	22	45	12	22	45	12	22	45	mA	
I_{OM}^- (Sink) @ $V_O=15\text{ V}$	12	20	45	12	20	45	12	20	45			
Supply Current, I^+ :												
	$V_O=7.5\text{ V}$, $R_L=\infty$	-	10	15	-	10	15	-	10	15	mA	
$V_O=0\text{ V}$, $R_L=\infty$	-	2	3	-	2	3	-	2	3			
Input Offset Voltage Temp. Drift, $\Delta V_{IO}/\Delta T^*$	-	5	-	-	6	-	-	8	-	$\mu\text{V}/^\circ\text{C}$		



TOP VIEW
S and T Suffixes



TOP VIEW
E Suffix

CA3160 Series devices have an on-chip frequency-compensation network. Supplementary phase-compensation or frequency roll-off (if desired) can be connected externally between terminals 1 and 8.

Fig. 1 - Functional diagrams of the CA3160 Series.

Linear Integrated Circuits

CA3160, CA3160A, CA3160B Types

TYPICAL VALUES INTENDED ONLY FOR DESIGN GUIDANCE

CHARACTERISTIC	TEST CONDITIONS	CA3160B (T, S)	CA3160A (T, S, E)	CA3160 (T, S, E)	UNITS
	$V^+ = +7.5\text{ V}$ $V^- = -7.5\text{ V}$ $T_A = 25^\circ\text{C}$ (Unless Otherwise Specified)				
Input Offset Voltage Adjustment Range	10 k Ω across Terms. 4 and 5 or 4 and 1	± 22	± 22	± 22	mV
Input Resistance, R_I		1.5	1.5	1.5	T Ω
Input Capacitance, C_I	f = 1 MHz	4.3	4.3	4.3	pF
Equivalent Input Noise Voltage, e_n	BW = 0.2 MHz $R_S = 1\text{ M}\Omega$ $R_S = 10\text{ M}\Omega$	40	40	40	μV
		50	50	50	
Equivalent Input Noise Voltage, e_n	$R_S = 100\ \Omega$ 1 kHz 10 kHz	72	72	72	nV $\sqrt{\text{Hz}}$
		30	30	30	
Unity Gain Crossover Frequency, f_T		4	4	4	MHz
Slew Rate, SR:		10	10	10	V/ μs
Transient Response: Rise Time, t_r	$C_L = 25\text{ pF}$ $R_L = 2\text{ k}\Omega$ (Voltage Follower)	0.09	0.09	0.09	μs
		10	10	10	%
Settling Time (4 V_{p-p} Input to $<0.1\%$)		1.8	1.8	1.8	μs

CHARACTERISTIC	TEST CONDITIONS	CA3160B (T, S)	CA3160A (T, S, E)	CA3160 (T, S, E)	UNITS
	$V^+ = 5\text{ V}$ $V^- = 0\text{ V}$ $T_A = 25^\circ\text{C}$ (Unless Otherwise Specified)				
Input Offset Voltage, V_{IO}		1	2	6	mV
Input Offset Current, I_{IO}		0.1	0.1	0.1	pA
Input Current, I_I		2	2	2	pA
Common-Mode Rejection Ratio, CMRR		100	90	80	dB
Large-Signal Voltage Gain, A_{OL}	$V_O = 4\text{ V}_{p-p}$ $R_L = 5\text{ k}\Omega$	100 k	100 k	100 k	V/V
		100	100	100	dB
Common-Mode Input Voltage Range, V_{ICR}		0 to 2.8	0 to 2.8	0 to 2.8	V
Supply Current, I^+	$V_O = 5\text{ V}$, $R_L = \infty$	300	300	300	μA
	$V_O = 2.5\text{ V}$, $R_L = \infty$	500	500	500	
Power Supply Rejection Ratio, $\Delta V_{IO}/\Delta V^+$		200	200	200	$\mu\text{V}/\text{V}$

CA3160, CA3160A, CA3160B Types

MAXIMUM RATINGS, *Absolute-Maximum Values*

DC SUPPLY VOLTAGE (Between V^+ and V^- Terminals)	16 V
DIFFERENTIAL-MODE INPUT VOLTAGE	± 8 V
COMMON-MODE DC INPUT VOLTAGE... ($V^+ + 8$ V) to ($V^- - 0.5$ V)	
INPUT-TERMINAL CURRENT	1 mA
DEVICE DISSIPATION:	
WITHOUT HEAT SINK -	
UP TO 55°C	630 mW
ABOVE 55°C	Derate linearly 6.67 mW/°C
WITH HEAT SINK -	
UP TO 90°C	1 W
ABOVE 90°C	Derate linearly 16.7 mW/°C

TEMPERATURE RANGE:

OPERATING (All Types) -55 to +125°C

STORAGE (All Types) -65 to +150°C

OUTPUT SHORT-CIRCUIT

DURATION*

LEAD TEMPERATURE

(DURING SOLDERING):

AT DISTANCE 1/16 \pm 1/32 INCH

(1.59 \pm 0.79 MM) FROM CASE

FOR 10 SECONDS MAX. +265°C

*Short circuit may be applied to ground or to either supply.

Fig.2 - Schematic diagram of the CA3160 Series.

CIRCUIT DESCRIPTION

Fig.3 is a block diagram of the CA3160 series COS/MOS Operational Amplifiers. The input terminals may be operated down to 0.5 V below the negative supply rail, and the output can be swung very close to either supply rail in many applications. Consequently, the CA3160 series circuits are ideal for single-supply operation. Three class A amplifier stages, having the individual gain capability and current consumption shown in Fig.3, provide the total gain of the CA3160. A biasing circuit provides two potentials for common use in the first and second stages. Terminals 8 and 1 can be used to supplement the internal phase compensation network if

additional phase compensation or frequency roll-off is desired. Terminals 8 and 4 can also be used to strobe the output stage into a low quiescent current state. When Terminal 8 is tied to the negative supply rail (Terminal 4) by mechanical or electrical means, the output potential at Terminal 6 essentially rises to the positive supply-rail potential at Terminal 7. This condition of essentially zero current drain in the output stage under the strobed "OFF" condition can only be achieved when the ohmic load resistance presented to the amplifier is very high (e.g., when the amplifier output is used to drive COS/MOS digital circuits in comparator applications).

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CA3160, CA3160A, CA3160B Types

Input Stages — The circuit of the CA3160 is shown in Fig.2. It consists of a differential input stage using PMOS field-effect transistors (Q6, Q7) working into a mirror-pair of bipolar transistors (Q9, Q10) functioning as load resistors together with resistors R3 through R6. The mirror-pair transistors also function as a differential-to-single-ended converter to provide base drive to the second-stage bipolar transistor (Q11). Offset nulling, when desired, can be effected by connecting a 100,000-ohm potentiometer across Terms. 1 and 5 and the potentiometer slider arm to Term. 4. Cascode-connected PMOS transistors Q2, Q4, are the constant-current source for the input stage. The biasing circuit for the constant-current source is subsequently described. The small diodes D5 through D7 provide gate-oxide protection against high-voltage transients, e.g., including static electricity during handling for Q6 and Q7.

Second-Stage — Most of the voltage gain in the CA3160 is provided by the second amplifier stage, consisting of bipolar transistor Q11 and its cascode-connected load resistance provided by PMOS transistors Q3 and Q5. The source of bias potentials for these PMOS transistors is described later. Miller Effect compensation (roll off) is accomplished by means of the 30-pF capacitor and 2-k Ω resistor connected between the base and collector of transistor Q11. These internal components provide sufficient compensation for unity gain operation in most applications. However, additional compensation, if desired, may be used between Terminals 1 and 8.

Bias-Source Circuit — At total supply voltages, somewhat above 8.3 volts, resistor R2 and zener diode Z1 serve to establish a voltage of 8.3 volts across the series-connected circuit, consisting of resistor R1, diodes D1 through D4, and PMOS transistor Q1. A tap at the junction of resistor R1 and diode D4 provides a gate-bias potential of about 4.5 volts for PMOS transistors Q4 and Q5 with respect to Terminal 7. A potential of

about 2.2 volts is developed across diode-connected PMOS transistor Q1 with respect to Terminal 7 to provide gate bias for PMOS transistors Q2 and Q3. It should be noted that Q1 is "mirror-connected"† to both Q2 and Q3. Since transistors Q1, Q2, Q3 are designed to be identical, the approximately 200-microampere current in Q1 establishes a similar current in Q2 and Q3 as constant-current sources for both the first and second amplifier stages, respectively.

At total supply voltages somewhat less than 8.3 volts, zener diode Z1 becomes non-conductive and the potential, developed across series-connected R1, D1-D4, and Q1, varies directly with variations in supply voltage. Consequently, the gate bias for Q4, Q5 and Q2, Q3 varies in accordance with supply-voltage variations. This variation results in deterioration of the power-supply-rejection ratio (PSRR) at total supply voltages below 8.3 volts. Operation at total supply voltages below about 4.5 volts results in seriously degraded performance.

Output Stage — The output stage consists of a drain-loaded inverting amplifier using COS/MOS transistors operating in the Class A mode. When operating into very high resistance loads, the output can be swung within millivolts of either supply rail. Because the output stage is a drain-loaded amplifier, its gain is dependent upon the load impedance. The transfer characteristics of the output stage for a load returned to the negative supply rail are shown in Fig.6. Typical op-amp loads are readily driven by the output stage. Because large-signal excursions are non-linear, requiring feedback for good waveform reproduction, transient delays may be encountered. As a voltage follower, the amplifier can achieve 0.01 per cent accuracy levels, including the negative supply rail.

† For general information on the characteristics of COS/MOS transistor-pairs in linear-circuit applications, see File No. 619, data bulletin on CA3600E "COS/MOS Transistor Array".

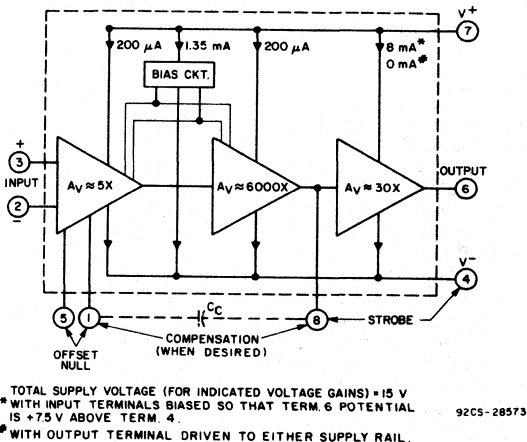


Fig. 3 — Block diagram of the CA3160 Series.

CA3160, CA3160A, CA3160B Types

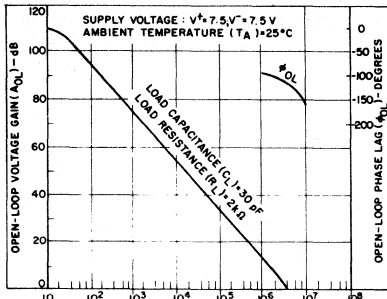


Fig. 4 - Open-loop voltage gain and phase shift vs. frequency.

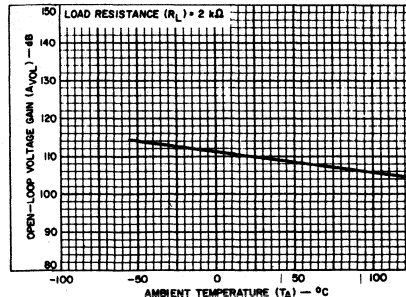


Fig. 5 - Open-loop gain vs. temperature.

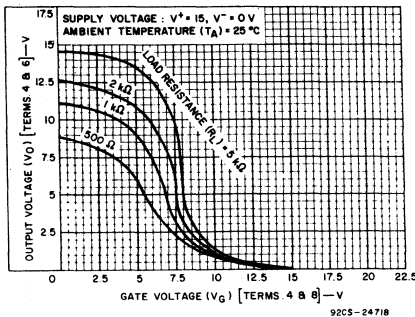


Fig. 6 - Voltage transfer characteristics of COS/MOS output stage.

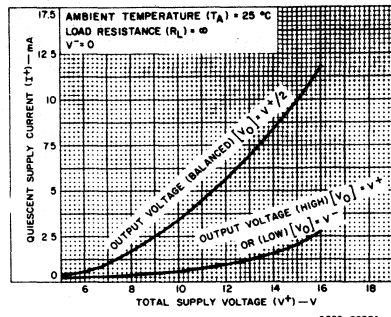


Fig. 7 - Quiescent supply current vs. supply voltage.

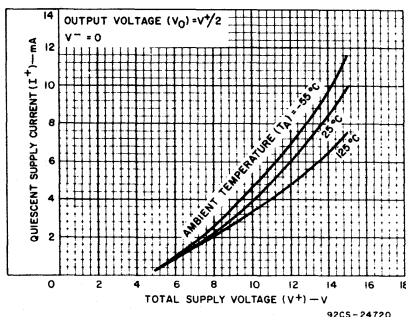


Fig. 8 - Quiescent supply current vs. supply voltage at several temperatures.

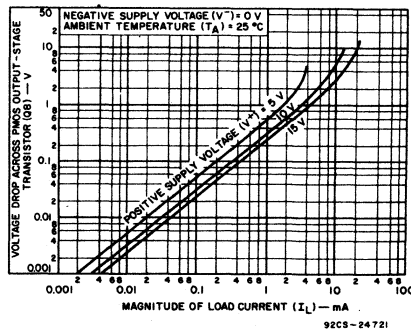


Fig. 9 - Voltage across PMOS output transistor (Q8) vs. load current.

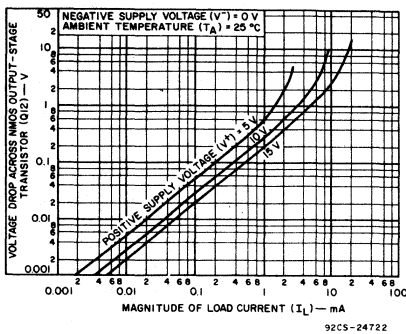


Fig. 10 - Voltage across NMOS output transistor (Q12) vs. load current.

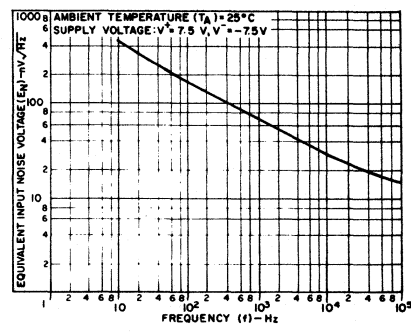


Fig. 11 - Equivalent noise voltage vs. frequency.

CA3160, CA3160A, CA3160B Types

Offset Nulling

Offset-voltage nulling is usually accomplished with a 100,000-ohm potentiometer connected across Terminals 1 and 5 and with the potentiometer slider arm connected to Terminal 4. A fine offset-null adjustment usually can be effected with the slider arm positioned in the mid-point of the potentiometer's total range.

Input Current Variation with Common-Mode Input Voltage

As shown in the Table of Electrical Characteristics, the input current for the CA3160 Series Op-Amps is typically 5 pA at $T_A=25^\circ\text{C}$ when Terminals 2 and 3 are at a common-mode potential of +7.5 volts with respect to negative supply Terminal 4. Fig. 12 contains

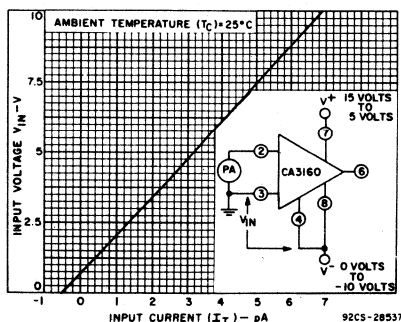


Fig. 12 — Input current vs. common-mode voltage.

data showing the variation of input current as a function of common-mode input voltage at $T_A=25^\circ\text{C}$. These data show that circuit designers can advantageously exploit these characteristics to design circuits which typically require an input current of less than 1 pA, provided the common-mode input voltage does not exceed 2 volts. As previously noted, the input current is essentially the result of the leakage current through the gate-protection diodes in the input circuit and, therefore, a function of the applied voltage. Although the finite resistance of the glass terminal-to-case insulator of the TO-5 package also contributes an increment of leakage current, there are useful compensating factors. Because the gate-protection network functions as if it is connected to Terminal 4 potential, and the TO-5 case of the CA3160 is also internally tied to Terminal 4, input terminal 3 is essentially "guarded" from spurious leakage currents.

Input-Current Variation with Temperature

The input current of the CA3160 Series circuits is typically 5 pA at 25°C . The major portion of this input current is due to leakage current through the gate-protective diodes in the input circuit. As with any semiconductor-junction device, including op amps with a junction-FET input stage, the leakage current approximately doubles for every 10°C increase in temperature. Fig. 13 provides data

on the typical variation of input bias current as a function of temperature in the CA3160.

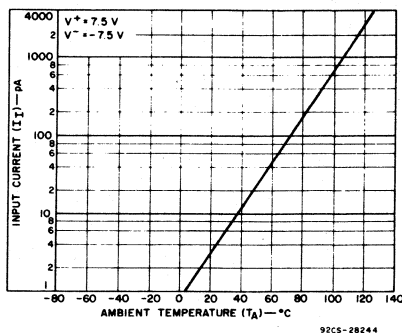


Fig. 13 — Input current vs. ambient temperature.

In applications requiring the lowest practical input current and incremental increases in current because of "warm-up" effects, it is suggested that an appropriate heat sink be used with the CA3160. In addition, when "sinking" or "sourcing" significant output current the chip temperature increases, causing an increase in the input current. In such cases, heat-sinking can also very markedly reduce and stabilize input current variations.

Input-Offset-Voltage (V_{IO}) Variation with DC Bias vs. Device Operating Life

It is well known that the characteristics of a MOS/FET device can change slightly when a dc gate-source bias potential is applied to the device for extended time periods. The magnitude of the change is increased at high temperatures. Users of the CA3160 should be alert to the possible impacts of this effect if the application of the device involves extended operation at high temperatures with a significant differential dc bias voltage applied across Terminals 2 and 3. Fig. 14 shows typical data pertinent to shifts in offset voltage encountered with CA3160 devices in TO-5 packages during life testing. At lower temperatures (TO-5 and plastic) for example at 85°C , this change in voltage is considerably less. In typical linear applications where the differential voltage is small and symmetrical, these incremental changes are of about the same magnitude as those en-

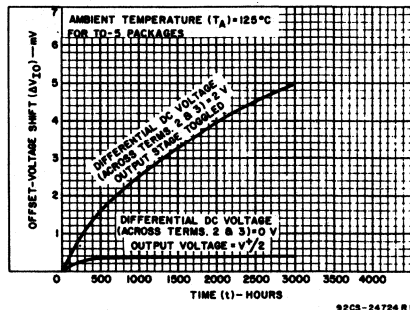


Fig. 14 — Typical incremental offset-voltage shift vs. operating life.

CA3160, CA3160A, CA3160B Types

countered in an operational amplifier employing a bipolar transistor input stage. The two-volt dc differential voltage example represents conditions when the amplifier output state is "toggled", e.g., as in comparator applications.

Power-Supply Considerations

Because the CA3160 is very useful in single-supply applications, it is pertinent to review some considerations relating to power-supply current consumption under both single- and dual-supply service. Figs. 15(a) and 15(b) show the CA3160 connected for both dual- and single-supply operation.

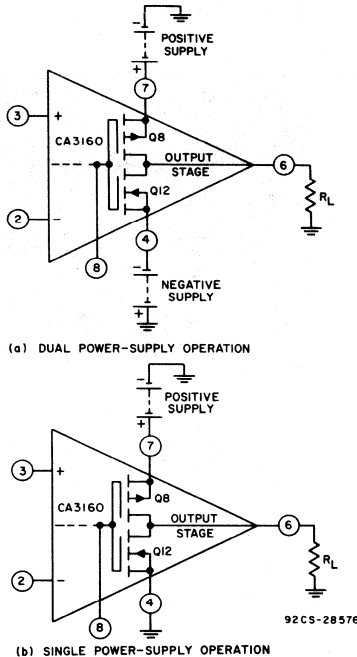


Fig. 15 — CA3160 output stage in dual and single power-supply operation.

Dual-supply operation: When the output voltage at Terminal 6 is zero-volts, the currents supplied by the two power supplies are equal. When the gate terminals of Q8 and Q12 are driven increasingly positive with respect to ground, current flow through Q12 (from the negative supply) to the load is increased and current flow through Q8 (from the positive supply) decreases correspondingly. When the gate terminals of Q8 and Q12 are driven increasingly negative with respect to ground, current flow through Q8 is increased and current flow through Q12 is decreased accordingly.

Single-supply operation: Initially, let it be assumed that the value of R_L is very high (or disconnected), and that the input-terminal bias (Terminals 2 and 3) is such that the output terminal (No. 6) voltage is at $V^+/2$, i.e., the voltage-drops across Q8 and Q12 are of equal magnitude. Fig. 7 shows typical quiescent supply-current vs. supply-voltage for the CA3160 operated under these conditions.

Since the output stage is operating as a Class A amplifier, the supply-current will remain constant under dynamic operating conditions as long as the transistors are operated in the linear portion of their voltage-transfer characteristics (see Fig. 6). If either Q8 or Q12 are swung out of their linear regions toward cut-off (a non-linear region), there will be a corresponding reduction in supply-current. In the extreme case, e.g., with Terminal 8 swung down to ground potential (or tied to ground), NMOS transistor Q12 is completely cut off and the supply-current to series-connected transistors Q8, Q12 goes essentially to zero. The two preceding stages in the CA3160, however, continue to draw modest supply-current (see the lower curve in Fig. 7) even though the output stage is strobed off. Fig. 15(a) shows a dual-supply arrangement for the output stage that can also be strobed off, assuming $R_L = \infty$, by pulling the potential of Terminal 8 down to that of Terminal 4.

Let it now be assumed that a load-resistance of nominal value (e.g., 2 kilohms) is connected between Terminal 6 and ground in the circuit of Fig. 15(b). Let it further be assumed again that the input-terminal bias (Terminals 2 and 3) is such that the output terminal (No. 6) voltage is a $V^+/2$. Since PMOS transistor Q8 must now supply quiescent current to both R_L and transistor Q12, it should be apparent that under these conditions the supply-current must increase as an inverse function of the R_L magnitude. Fig. 9 shows the voltage-drop across PMOS transistor Q8 as a function of load current at several supply voltages. Fig. 6 shows the voltage-transfer characteristics of the output stage for several values of load resistance.

Wideband Noise

From the standpoint of low-noise performance considerations, the use of the CA3160 is most advantageous in applications where in the source resistance of the input signal is in the order of 1 megohm or more. In this case, the total input-referred noise voltage is typically only $40 \mu\text{V}$ when the test-circuit amplifier of Fig. 16 is operated at a total supply voltage of 15 volts. This value of

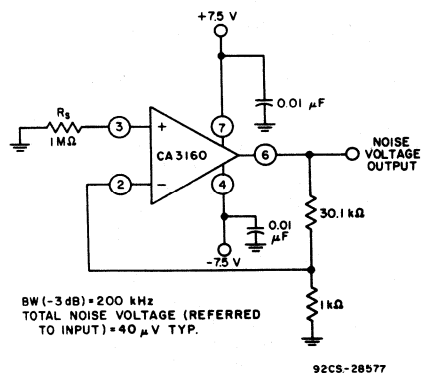
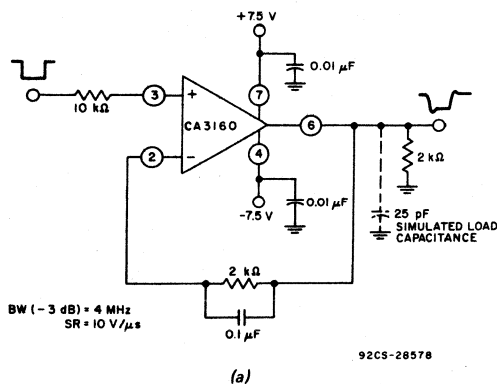


Fig. 16 — Test-circuit amplifier (30-dB gain) used for wideband noise measurements.

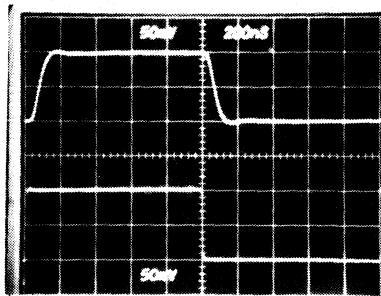
Linear Integrated Circuits

CA3160, CA3160A, CA3160B Types

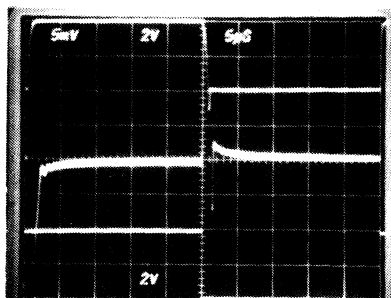
total input-referred noise remains essentially constant, even though the value of source resistance is raised by an order of magnitude. This characteristic is due to the fact that reactance of the input capacitance becomes a significant factor in shunting the source resistance. It should be noted, however, that for values of source resistance very much greater than 1 megohm, the total noise voltage generated can be dominated by the thermal noise contributions of both the feedback and source resistors.



(a)



(b) Small Signal Response
Top Trace: Output
Bottom Trace: Input



(c) Input-Output Difference Signal Showing Settling Time
Top Trace: Output Signal
Center Trace: Difference Signal 5 mV/div
Bottom Trace: Input Signal

Fig. 17 – Split-supply voltage follower with associated waveforms.

TYPICAL APPLICATIONS

Voltage Followers

Operational amplifiers with very high input resistances, like the CA3160, are particularly suited to service as voltage followers. Fig. 17 shows the circuit of a classical voltage follower, together with pertinent waveforms using the CA3160 in a split-supply configuration.

A voltage follower, operated from a single-supply, is shown in Fig. 18 together with related waveforms. This follower circuit is linear over a wide dynamic range, as illustrated by the reproduction of the output waveform in Fig. 18b with input-signal ramping. The waveforms in Fig. 18c show that the follower does not lose its input-to-output phase-sense, even though the input is being swung 7.5 volts below ground potential. This unique characteristic is an important attribute in both operational amplifier and comparator applications. Fig. 18c also shows the manner in which the COS/MOS output stage permits the output signal to swing down

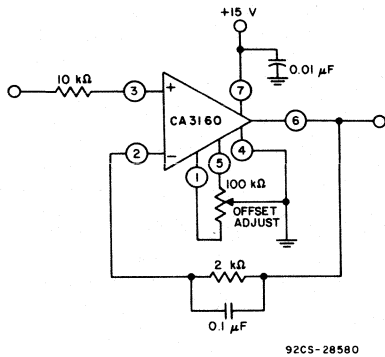
to the negative supply-rail potential (i.e., ground in the case shown). The digital-to-analog converter (DAC) circuit, described in the following section, illustrates the practical use of the CA3160 in a single-supply voltage-follower application.

9-Bit COS/MOS DAC

A typical circuit of a 9-bit Digital-to-Analog Converter (DAC)* is shown in Fig. 19. This system combines the concepts of multiple-switch COS/MOS IC's, a low-cost ladder network of discrete metal-oxide-film resistors, a CA3160 op amp connected as a follower, and an inexpensive monolithic regulator in a simple single power-supply arrangement. An additional feature of the DAC is that it is readily interfaced with COS/MOS input logic, e.g., 10-volt logic levels are used in the circuit of Fig. 19.

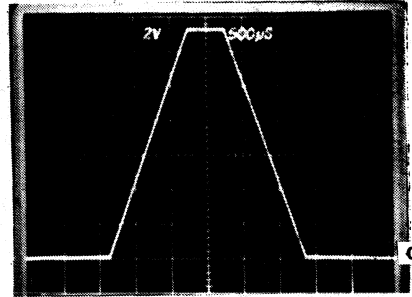
* "Digital-to-Analog Conversion Using the RCA-CD4007A COS/MOS IC", Application Note ICAN-6080.

CA3160, CA3160A, CA3160B Types

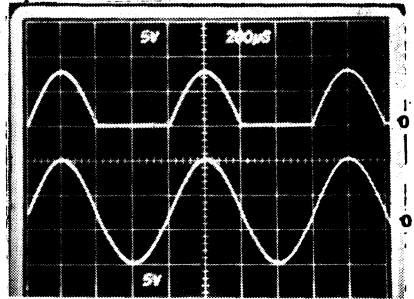


(a)

92CS-28580



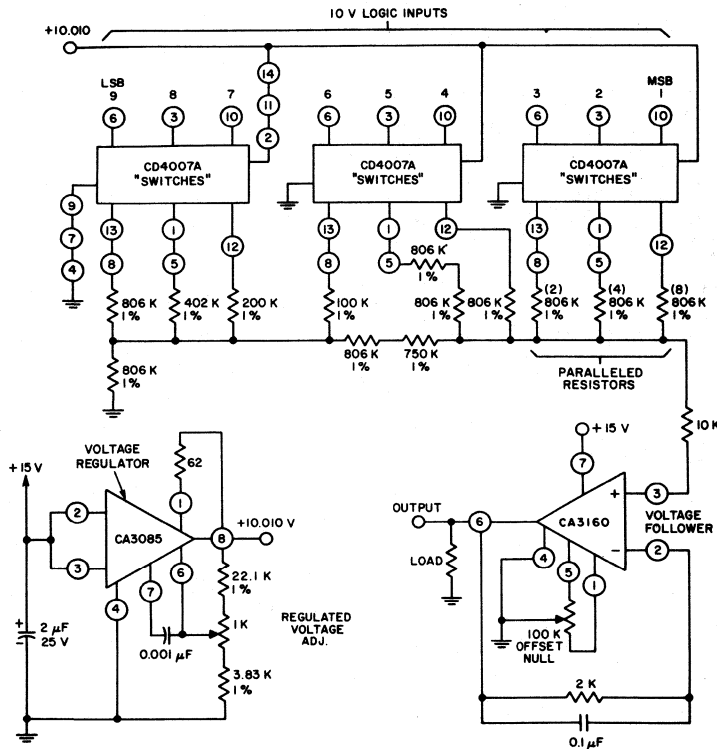
(b) Output signal with input-signal ramping.



(c) Output-Waveform with Ground-Reference Sine-Wave Input
Top Trace: Output
Bottom Trace: Input

92CS-28581R1

Fig. 18 — Single-supply voltage-follower with associated waveforms. (e.g., for use in single-supply D/A converter; see Fig.9 in ICAN-6080.)



BIT	REQUIRED RATIO-MATCH
1	STANDARD
2	±0.1%
3	±0.2%
4	±0.4%
5	±0.8%
6-9	±1% ABS.

ALL RESISTANCES IN OHMS

92CM-28582

Fig. 19 — 9-bit DAC using COS/MOS digital switches and CA3160.

Linear Integrated Circuits

CA3160, CA3160A, CA3160B Types

The circuit uses an R/2R voltage-ladder network, with the output-potential obtained directly by terminating the ladder arms at either the positive or the negative power-supply terminal. Each CD4007A contains three "inverters", each "inverter" functioning as a single-pole double-throw switch to terminate an arm of the R/2R network at either the positive or negative power-supply terminal. The resistor ladder is an assembly of one per cent tolerance metal-oxide film resistors. The five arms requiring the highest accuracy are assembled with series and parallel combinations of 806,000-ohm resistors from the same manufacturing lot.

A single 15-volt supply provides a positive bus for the CA3160 follower amplifier and feeds the CA3085 voltage regulator. A "scale-adjust" function is provided by the regulator output control, set to a nominal 10-volt level in this system. The line-voltage regulation (approximately 0.2%) permits a 9-bit accuracy to be maintained with variations of several volts in the supply. The

flexibility afforded by the COS/MOS building blocks simplifies the design of DAC systems tailored to particular needs.

Error-Amplifier in Regulated Power Supplies

The CA3160 is an ideal choice for error-amplifier service in regulated power supplies since it can function as an error-amplifier when the regulated output voltage is required to approach zero.

The circuit shown in Fig.20 uses a CA3160 as an error amplifier in a continuously adjustable 1-ampere power supply. One of the key features of this circuit is its ability to regulate down to the vicinity of zero volts with only one dc power supply input.

An RC network, connected between the base of the output drive transistor and the input voltage, prevents "turn-on overshoot", a condition typical of many operational-amplifier regulator circuits. As the amplifier becomes operational, this RC network ceases to have any influence on the regulator performance.

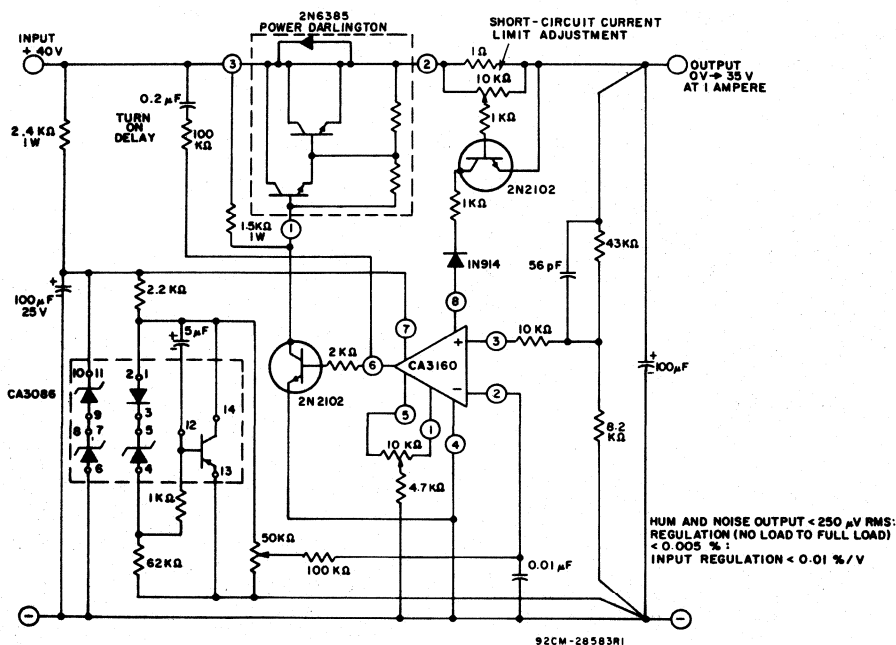


Fig.20 - Voltage regulator circuit (0.1 to 35 V at 1 A).

CA3160, CA3160A, CA3160B Types

Precision Voltage-Controlled Oscillator

The circuit diagram of a precision voltage-controlled oscillator is shown in Fig.21. The oscillator operates with a tracking error in the order of 0.02 percent and a temperature coefficient of 0.01%/°C. A multivibrator (A₁) generates pulses of constant amplitude (V) and width (T₂). Since the output (terminal 6) of A₁ (a CA3130) can swing within about 10 millivolts of either supply-rail, the output pulse amplitude (V) is essentially equal to V+. The average output voltage ($E_{avg} = V T_2/T_1$) is applied to the non-inverting input terminal of comparator A₂ via an integrating network R₃, C₂. Comparator A₂ operates to establish circuit conditions such that $E_{avg} = V_1$. This circuit condition is accomplished by feeding an output signal from terminal 6 of A₂ through R₄, D₄ to the inverting terminal (terminal 2)

of A₁; thereby adjusting the multivibrator interval, T₃.

Voltmeter With High Input Resistance

The voltmeter circuit shown in Fig.22 illustrates an application in which a number of the CA3160 characteristics are exploited. Range-switch SW₁ is ganged between input and output circuitry to permit selection of the proper output voltage for feedback to Terminal 2 via 10 KΩ current-limiting resistor. The circuit is powered by a single 8.4-volt mercury battery. With zero input signal, the circuit consumes somewhat less than 500 microamperes plus the meter current required to indicate a given voltage. Thus, at full-scale input, the total supply current rises to slightly more than 1500 microamperes.

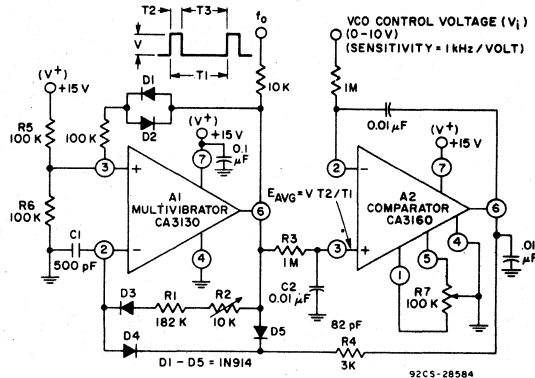


Fig.21 – Voltage-controlled oscillator.

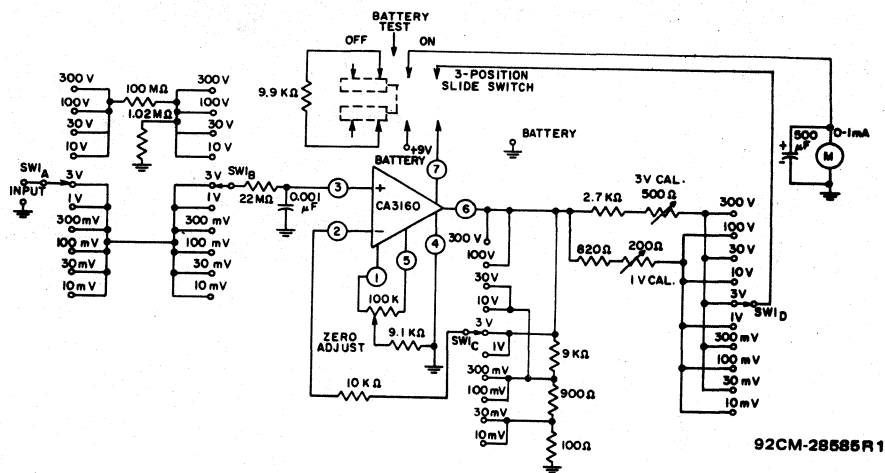


Fig.22 – High-input-resistance DC voltmeter.

Linear Integrated Circuits

CA3160, CA3160A, CA3160B Types

Function Generator

A function generator having a wide tuning range is shown in Fig.23. The adjustment range, in excess of 1,000,000/1, is accomplished by a single potentiometer. Three operational amplifiers are utilized: a CA3160 as a voltage follower, a CA3080 as a high-speed comparator, and a second CA3080A

as a programmable current source. Three variable capacitors C1, C2, and C3 shape the triangular signal between 500 kHz and 1 MHz. Capacitors C4, C5, and the trimmer potentiometer in series with C5 maintain essentially constant ($\pm 10\%$) amplitude up to 1 MHz.

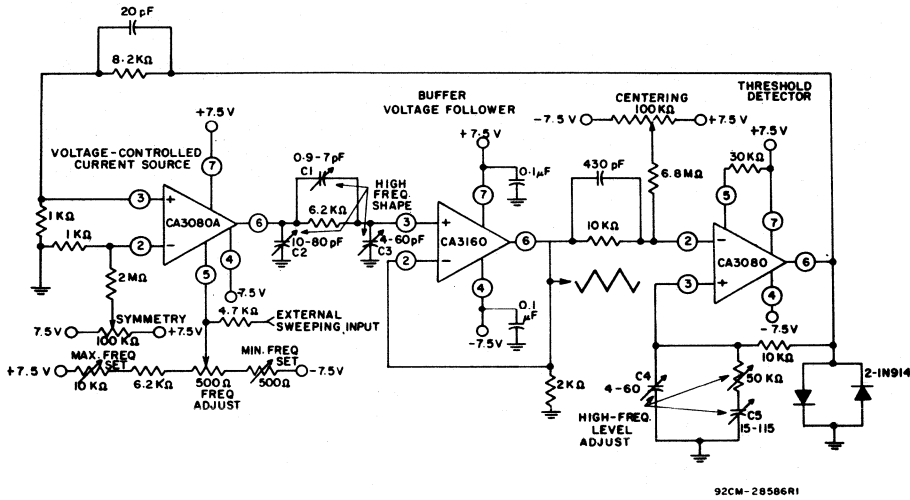
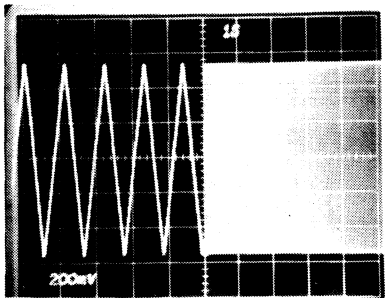
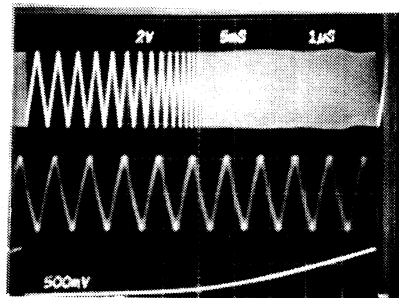


Fig.23(a) – 1,000,000/1 single-control function generator – 1 MHz to 1 Hz.



(b) – Two-tone output signal from the function generator. A square-wave signal modulates the external sweeping input to produce 1 Hz and 1 MHz, showing the 1,000,000/1 frequency range of the function generator.

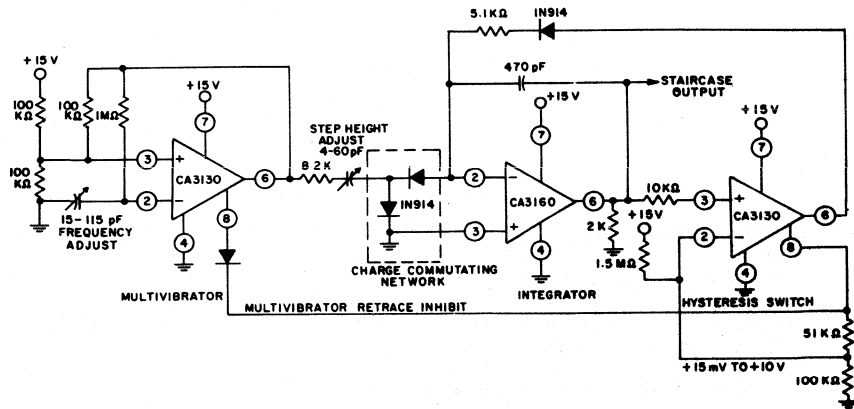


(c) – Triple-trace of the function generator sweeping to 1 MHz. The bottom trace is the sweeping signal and the top trace is the actual generator output. The center trace displays the 1 MHz signal via delayed oscilloscope triggering of the upper swept output signal.

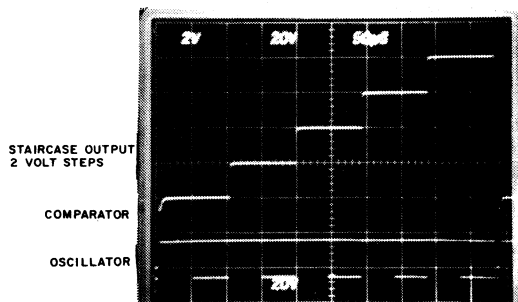
CA3160, CA3160A, CA3160B Types

Staircase Generator

Fig.24 shows a staircase generator circuit utilizing three COS/MOS operational amplifiers. Two CA3130's are used; one as a multivibrator, the other as a hysteresis switch. The third amplifier, a CA3160, is used as a linear staircase generator.



92CM-28587R1



92CS-28596

(b) - Staircase Generator Waveform
Top Trace: Staircase Output
2 Volt Steps
Center Trace: Comparator
Bottom Trace: Oscillator

Picoammeter Circuit

Fig. 25 is a current-to-voltage converter configuration utilizing a CA3160 and CA3140 to provide a picoampere meter for ± 3 pA full-scale meter deflection. By placing Terminals 2 and 4 of the CA3160 at ground potential, the CA3160 input is operated in the "guarded mode". Under this operating condition, even slight leakage resistance present between Terminals 3 and 2 or between Terminals 3 and 4 would result in zero voltage across this leakage resistance, thus substantially reducing the leakage current.

If the CA3160 is operated with the same voltage on input Terminals 3 and 2 as on Terminal 4, a further reduction in the input current to the less than one picoampere level can be achieved as shown in Fig. 12.

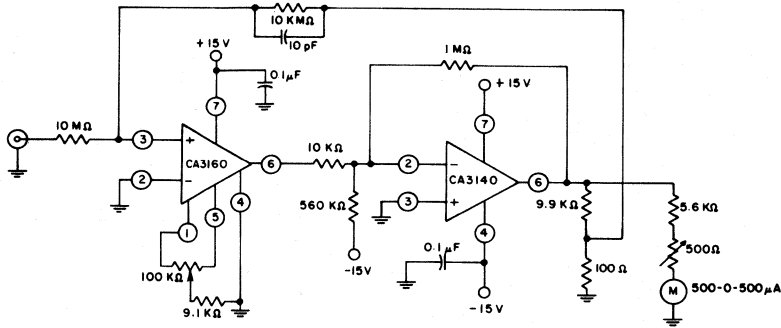
To further enhance the stability of this circuit, the CA3160 can be operated with its

output (Terminal 6) near ground, thus markedly reducing the dissipation by reducing the supply current to the device.

The CA3140 stage serves as a X100 gain stage to provide the required plus and minus output swing for the meter and feedback network. A 100-to-1 voltage divider network consisting of a 9.9-K Ω resistor in series with a 100-ohm resistor sets the voltage at the 10-KM Ω resistor (in series with Terminal 3) to ± 30 mV full-scale deflection. This 30-mV signal results from ± 3 volts appearing at the top of the voltage divider network which also drives the meter circuitry.

By utilizing a switching technique in the meter circuit and in the 9.9 K Ω and 100-ohm network similar to that used in voltmeter circuit shown in Fig. 22, a current range of 3 pA to 1 nA full scale can be handled with the single 10-KM Ω resistor.

CA3160, CA3160A, CA3160B Types



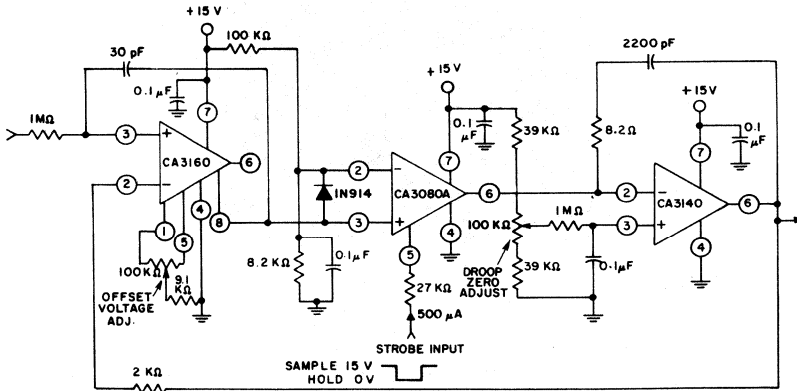
92CM-28589R1

Fig.25 — Current-to-voltage converter to provide a picoammeter with $\pm 3 \text{ pA}$ full-scale deflection.

Single-Supply Sample-and-Hold System

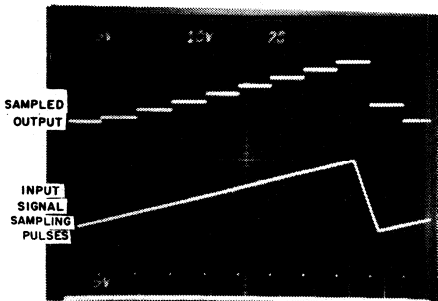
Fig. 26 shows a single-supply sample-and-hold system using a CA3160 to provide a high input impedance and an input-voltage range of 0 to 10 volts. The output from the input buffer integrator network is coupled to a CA3080A. The CA3080A functions as a strobeable current source for the CA3140 output integrator and storage capacitor. The CA3140 was chosen because of its low output impedance and constant gain-bandwidth

product. Pulse "droop" during the hold interval can be reduced to zero by adjusting the 100-KΩ bias-voltage potentiometer on the positive input of the CA3140. This zero adjustment sets the CA3080A output voltage at its zero current position. In this sample-and-hold circuit it is essential that the amplifier bias current be reduced to zero to minimize output signal current during the hold mode. Even with 320 mV at the amplifier bias circuit terminal (5) at least $\pm 100 \text{ pA}$ of output current will be available.

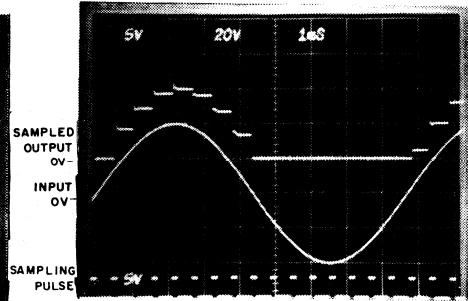


92CM-28590

Fig.26(a) — Single-supply sample-and-hold system—input 0-to-10 volts.



(b) — Sample-and-hold waveform.
Top Trace: Sampled Output
Center Trace: Input Signal
Bottom Trace: Sampling Pulses



(c) — Sample-and-hold waveform.
Top Trace: Sampled Output
Center Trace: Input
Bottom Trace: Sampling Pulse

92CS-28595

CA3160, CA3160A, CA3160B Types

Wien Bridge Oscillator

A simple, single-supply Wien Bridge oscillator using a CA3160 is shown in Fig. 27. A pair of parallel-connected 1N914 diodes comprise the gain-setting network which standardizes the output voltage at approximately 1.1 volts. The 500-ohm potentiometer is adjusted so that the oscillator will always start and the oscillation will be maintained. Increasing the amplitude of the voltage may lower the threshold level for starting and for sustaining the oscillation, but will introduce more distortion.

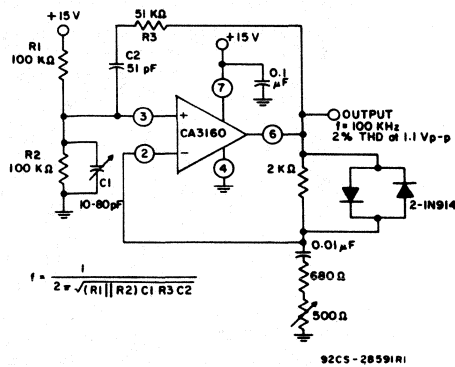


Fig.27 - Single-supply Wien Bridge oscillator.

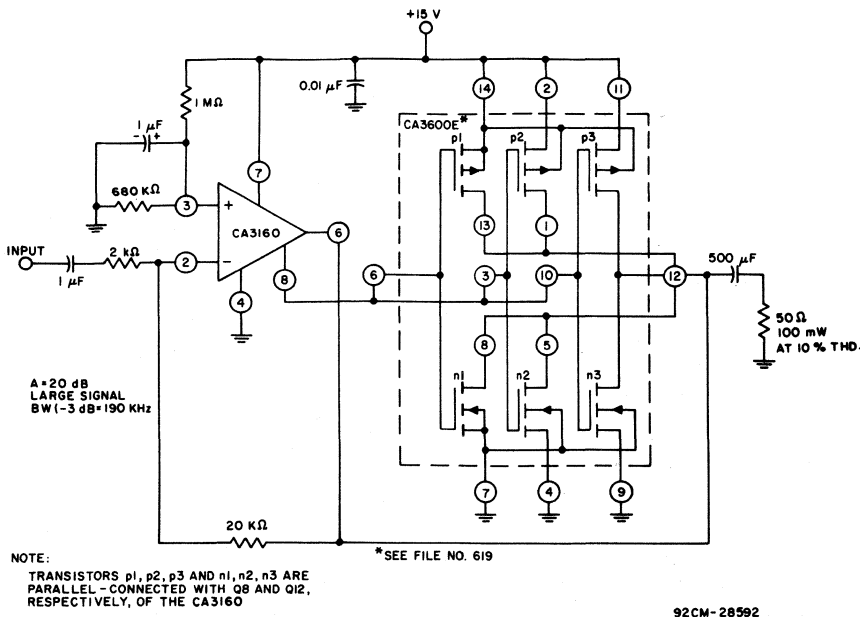
$$f = \frac{1}{2\pi \sqrt{(R1 || R2) C1 R3 C2}}$$

Operation with Output-Stage Power-Booster

The current sourcing and sinking capability of the CA3160 output stage is easily supplemented to provide power-boost capability. In the circuit of Fig.28, three COS/MOS transistor-pairs in a single CA3600 IC array are shown parallel-connected with the output stage in the CA3160. In the Class A mode of CA3600E shown, a typical device consumes

20 mA of supply current at 15-V operation. This arrangement boosts the current-handling capability of the CA3160 output stage by about 2.5X.

The amplifier circuit in Fig. 28 employs feedback to establish a closed-loop gain of 20 dB. The typical large-signal-bandwidth (-3 dB) is 190 kHz.



NOTE:
TRANSISTORS p1, p2, p3 AND n1, n2, n3 ARE
PARALLEL-CONNECTED WITH Q8 AND Q12,
RESPECTIVELY, OF THE CA3160

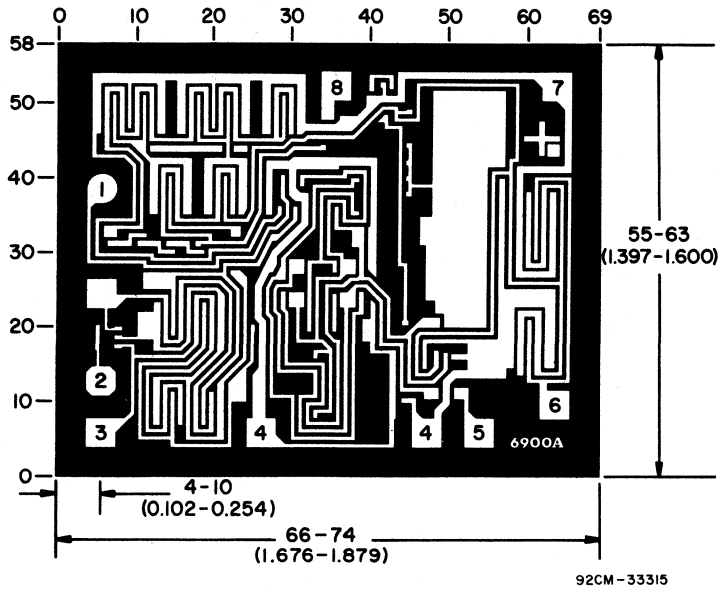
*SEE FILE NO. 619

92CM-28592

Fig.28 - COS/MOS transistor array (CA3600E) connected as power booster in the output stage of the CA3160.

Linear Integrated Circuits

CA3160, CA3160A, CA3160B Types



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

The photograph and dimensions represent a chip when it is part of the wafer. When the wafer is cut into chips the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

Dual BiMOS Operational Amplifiers

With MOS/FET Input, Bipolar Output

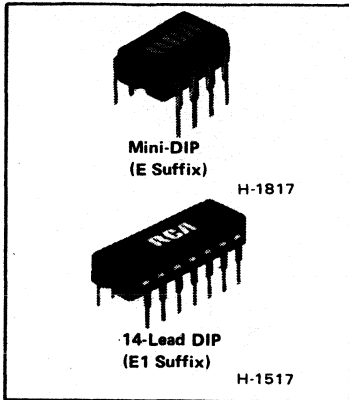
Features:

- Dual version of CA3140
- Internally compensated
- MOS/FET input stage
 - (a) Very high input impedance (Z_{IN}) - $1.5 T\Omega$ typ.
 - (b) Very low input current (I_i) - 10 pA typ. at $\pm 15 \text{ V}$
 - (c) Wide common-mode input-voltage range (V_{ICR}) - can be swung 0.5 volt below negative supply-voltage rail
 - (d) Rugged input stage - bipolar diode protected
- Directly replaces industry types 747 and 1458 in most applications
- Operation from 4-to-36 volts single or dual supplies
- Characterized for $\pm 15\text{-volt}$ operation and for TTL supply systems with operation down to 4 volts

- Wide bandwidth - 4.5 MHz unity gain at $\pm 15 \text{ V}$ or 30 V
- High voltage-follower slew rate - $9/\text{V}\mu\text{s}$
- Output swings to within 0.5 volt of negative supply at $V^+ = 5 \text{ V}$, $V^- = 0$

Applications:

- Ground-referenced single-supply amplifiers in automobile and portable instrumentation
- Sample and hold amplifiers
- Long-duration timers/multivibrators (microseconds - minutes - hours)
- Photocurrent instrumentation
- Active filters
- Intrusion alarm systems
- Comparators
- Instrumentation amplifiers
- Function generators
- Power supplies



The RCA-CA3240A and CA3240 are dual versions of the popular CA3140-series integrated circuit operational amplifiers. They combine the advantages of MOS and bipolar transistors on the same monolithic chip. The gate-protected MOS/FET (PMOS) input transistors provide high input impedance and a wide common-mode input voltage range (typically to 0.5 V below the negative supply rail). The bipolar output transistors allow a wide output voltage swing and provide a high output current capability.

The CA3240A and CA3240 are supplied in the 8-lead dual-in-line plastic package (Mini-DIP, E suffix), and in the 14-lead dual-in-line plastic package (E1 suffix). They are pin-compatible with the industry standard 747 and 1458 operational amplifiers in similar packages. The CA3240A and CA3240 have an operating-temperature range of -40 to $+85^\circ \text{C}$. The offset null feature is available only when these types are supplied in the 14-lead dual-in-line plastic package (E1 suffix). The CA3240 is also available in chip form (H suffix).

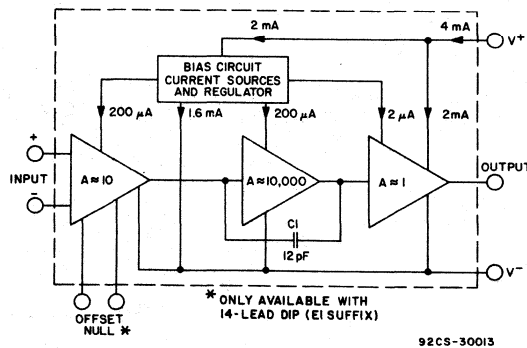


Fig. 1 — Block diagram of one-half CA3240 series.

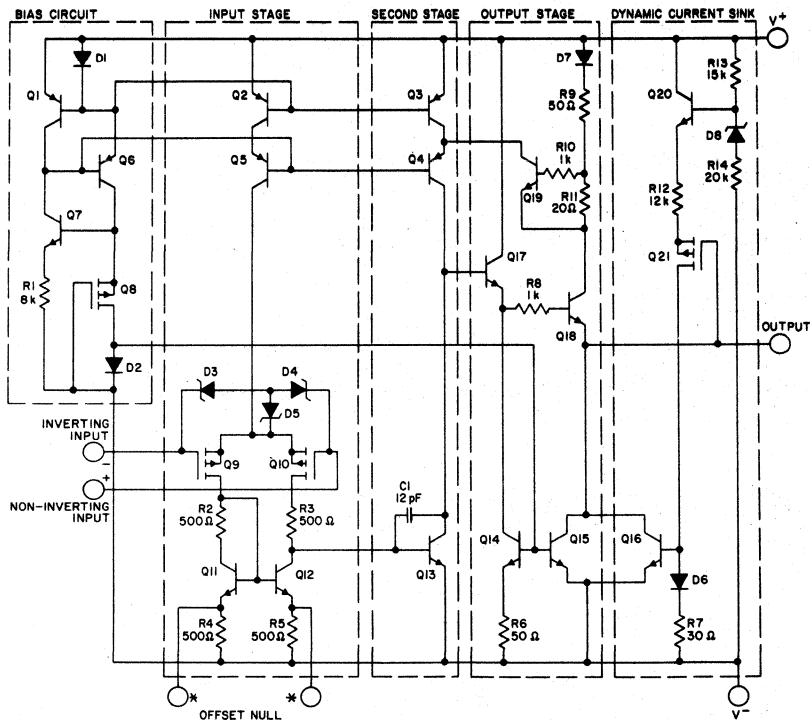
Linear Integrated Circuits

CA3240, CA3240A Types

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE (BETWEEN V^+ AND V^- TERMINALS)	36 V
OPERATING VOLTAGE RANGE	4 to 36 V or ± 2 to ± 18 V
DIFFERENTIAL-MODE INPUT VOLTAGE	± 8 V
COMMON-MODE DC INPUT VOLTAGE	(V^+ +8 V) to (V^- -0.5 V)
INPUT-TERMINAL CURRENT	1 mA
DEVICE DISSIPATION:	
UP TO 55°C	630 mW
ABOVE 55°C	Derate linearly 6.67 mW/°C
TEMPERATURE RANGE:	
OPERATING	-40 to +85°C
STORAGE	-65 to +150°C
OUTPUT SHORT-CIRCUIT DURATION [●]	UNLIMITED
LEAD TEMPERATURE (DURING SOLDERING):	
AT DISTANCE 1/16 \pm 1/32 INCH (1.59 \pm 0.79 MM)	
FROM CASE FOR 10 SECONDS MAX.	+265°C

[●] Short circuit may be applied to ground or to either supply. Temperatures and/or supply voltages must be limited to keep dissipation within maximum rating.



ALL RESISTANCE VALUES ARE IN OHMS.
* ONLY AVAILABLE WITH 14-LEAD DIP (E1 SUFFIX)

92CL-30014

Fig. 2 — Schematic diagram of one-half CA3240 series.

Circuit Description

The schematic diagram of one amplifier section of the CA3240 is shown in Fig. 2. It consists of a differential amplifier stage using PMOS transistors Q9 and Q10 with gate-to-source protection against static discharge damage provided by zener diodes D3, D4, and D5. Constant current bias is applied to the differential amplifier from transistors Q2

and Q5 connected as a constant-current source. This assures a high common-mode rejection ratio. The output of the differential amplifier is coupled to the base of gain stage transistor Q13 by means of an n-p-n current mirror that supplies the required differential-to-single-ended conversion. Provision for offset null for types in the 14-lead plastic package (E1 suffix) is provided through the use of this current mirror.

CA3240, CA3240A Types

The gain stage transistor Q13 has a high-impedance active load (Q3 and Q4) to provide maximum open-loop gain. The collector of Q13 directly drives the base of the compound emitter-follower output stage. Pull-down for the output stage is provided by two independent circuits: (1) constant-current-connected transistors Q14 and Q15 and (2) dynamic current-sink transistor Q16 and its associated circuitry. *The level of pull-down current is constant at about 1 mA for Q15 and varies from 0 to 18 mA for Q16 depending on the magnitude of the voltage between the output terminal and V^+ . The dynamic current sink becomes active whenever the output terminal is more negative*

than V^+ by about 15 V. When this condition exists, transistors Q21 and Q16 are turned on causing Q16 to sink current from the output terminal to V^- . This current always flows when the output is in the linear region, either from the load resistor or from the emitter of Q18 if no load resistor is present. The purpose of this dynamic sink is to permit the output to go within 0.2 V ($V_{CE(sat)}$) of V^- with a 2-k Ω load to ground. *When the load is returned to V^+ , it may be necessary to supplement the 1 mA of current from Q15 in order to turn on the dynamic current sink (Q16). This may be accomplished by placing a resistor (approx. 2 k Ω) between the output and V^- .*

ELECTRICAL CHARACTERISTICS FOR EQUIPMENT DESIGN

At $V^+ = 15$ V, $V^- = 15$ V, $T_A = 25^\circ\text{C}$ Unless Otherwise Specified

CHARACTERISTIC	LIMITS						UNITS
	CA3240A			CA3240			
	Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage, $ V_{IO} $	—	2	5	—	5	15	mV
Input Offset Current, $ I_{IO} $	—	0.5	20	—	0.5	30	pA
Input Current, I_I	—	10	40	—	10	50	pA
Large-Signal Voltage Gain, A_{OL} [•] (See Figs. 4, 19)	20 k	100 k	—	20 k	100 k	—	V/V
	86	100	—	86	100	—	dB
Common-Mode Rejection Ratio, $CMRR$ (See Fig. 9)	—	32	320	—	32	320	$\mu\text{V/V}$
	70	90	—	70	90	—	dB
Common-Mode Input-Voltage Range, V_{ICR} (See Fig. 16)	—15	—15.5 to +12.5	12	—15	—15.5 to +12.5	11	V
Power-Supply Rejection Ratio, $\frac{\Delta V_{IO}}{\Delta V}$ $PSRR$ (See Fig. 11)	—	100	150	—	100	150	$\mu\text{V/V}$
	76	80	—	76	80	—	dB
Maximum Output Voltage, [■] (See Figs. 22, 16)	V_{OM}^+	+12	13	—	+12	13	V
	V_{OM}^-	—14	—14.4	—	—14	—14.4	
Maximum Output Voltage, [†] V_{OM}^-	0.4	0.13	—	0.4	0.13	—	V
Supply Current, I^+ (See Fig. 7) For Both Amps.	—	8	12	—	8	12	mA
Total Device Dissipation, P_D	—	240	360	—	240	360	mW

[•] At $V_O = 26$ V_{p-p}, +12 V, —14 V and $R_L = 2$ k Ω .

[■] At $R_L = 2$ k Ω .

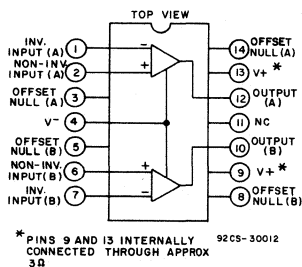
[†] At $V^+ = 5$ V, $V^- = \text{GND}$, $I_{\text{Sink}} = 200$ μA .

Linear Integrated Circuits

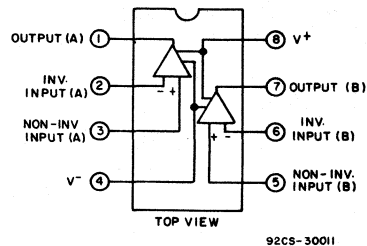
CA3240, CA3240A Types

TYPICAL ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	TEST CONDITIONS $V^+ = +15\text{ V}$ $V^- = -15\text{ V}$ $T_A = 25^\circ\text{C}$	TYPICAL VALUES		UNITS
		CA3240A	CA3240	
Input Offset Voltage Adjustment Resistor (E1 Package Only)	Typ. Value of Resistor Between Terms. 4 and 3(5) or Between 4 and 14(8) to Adjust Max. V_{IO}	18	4.7	$k\Omega$
Input Resistance R_I		1.5	1.5	$T\Omega$
Input Capacitance C_I		4	4	pF
Output Resistance R_O		60	60	Ω
Equivalent Wideband Input Noise Voltage (See Fig. 21)	$BW=140\text{ kHz}$ $R_S = 1\text{ M}\Omega$	48	48	μV
Equivalent Input Noise Voltage (See Fig. 10)	$f = 1\text{ kHz}$	$R_S =$	40	$n\text{V}/\sqrt{\text{Hz}}$
	$f = 10\text{ kHz}$	100. Ω	12	
Short-Circuit Current to Opposite Supply Source	I_{OM}^+		40	mA
	Sink I_{OM}^-		11	
Gain-Bandwidth Product (See Figs. 5 and 19)	f_T		4.5	MHz
Slew Rate (See Fig. 6)	SR		9	$\text{V}/\mu\text{s}$
Transient Response: Rise Time	t_r	$R_L = 2\text{ k}\Omega$	0.08	μs
		$C_L = 100\text{ pF}$	10	%
Settling Time at 10 V_{p-p} (See Fig. 17)	t_s	$R_L = 2\text{ k}\Omega$	4.5	μs
		$C_L = 100\text{ pF}$ Voltage Follower	1.4	
Crosstalk	$f = 1\text{ kHz}$	120	120	dB



E1 Suffix
Pin compatible with the industry-standard 747



E Suffix
Pin compatible with the industry-standard 1458

Fig. 3 - Functional diagrams.

CA3240, CA3240A Types

ELECTRICAL CHARACTERISTICS FOR EQUIPMENT DESIGN

At $V^+ = 15\text{ V}$, $V^- = 15\text{ V}$, $T_A = -40$ to $+85^\circ\text{C}$ Unless Otherwise Specified

CHARACTERISTIC	TYPICAL VALUES		UNITS
	CA3240A	CA3240	
Input Offset Voltage, $ V_{IO} $	3	10	mV
Input Offset Current, $ I_{IO} $	32	32	pA
Input Current, I_I	640	640	pA
Large-Signal Voltage Gain, A_{OL} (See Figs. 4, 19)	63 k	63 k	V/V
	96	96	dB
Common-Mode Rejection Ratio, CMRR (See Fig. 9)	32	32	$\mu\text{V/V}$
	90	90	dB
Common-Mode Input-Voltage Range, V_{ICR} (See Fig. 16)	-15	-15	V
	to +12.3	to +12.3	
Power-Supply Rejection Ratio, $\frac{\Delta V_{IO}}{\Delta V}$ PSRR (See Fig. 11)	150	150	$\mu\text{V/V}$
	76	76	dB
Maximum Output Voltage, V_{OM} (See Figs. 16, 22)	V_{OM}^+	12.4	V
	V_{OM}^-	-14.2	
Supply Current, I^+ (See Fig. 7) For Both Amps.	8.4	8.4	mA
Total Device Dissipation, P_D	252	252	mW
Temperature Coefficient of Input Offset Voltage, $\Delta V_{IO}/\Delta T$	15	15	$\mu\text{V}/^\circ\text{C}$

• At $V_O = 26\text{ V}_{p-p}$, $+12\text{ V}$, -14 V and $R_L = 2\text{ k}\Omega$.

■ At $R_L = 2\text{ k}\Omega$.

♦ At $T_A = 85^\circ\text{C}$

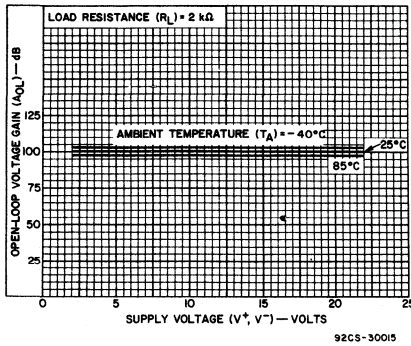


Fig. 4 — Open-loop voltage gain as a function of supply voltage and temperature.

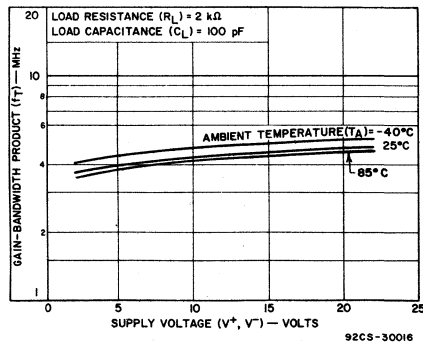


Fig. 5 — Gain-bandwidth product as a function of supply voltage and temperature.

Linear Integrated Circuits

CA3240, CA3240A Types

TYPICAL ELECTRICAL CHARACTERISTICS FOR DESIGN GUIDANCE
At $V^+ = 5\text{ V}$, $V^- = 0\text{ V}$, $T_A = 25^\circ\text{C}$

CHARACTERISTIC		TYPICAL VALUES		UNITS
		CA3240A	CA3240	
Input Offset Voltage,	$ V_{IO} $	2	5	mV
Input Offset Current,	$ I_{IO} $	0.1	0.1	pA
Input Current,	I_I	2	2	pA
Input Resistance		1	1	$T\Omega$
Large-Signal Voltage Gain, (See Figs. 4, 19)	A_{OL}	100 k	100 k	V/V
		100	100	dB
Common-Mode Rejection Ratio, CMRR		32	32	$\mu\text{V/V}$
		90	90	dB
Common-Mode Input-Voltage Range, (See Fig. 22)	V_{ICR}	-0.5	-0.5	V
		2.6	2.6	
Power-Supply Rejection Ratio, PSRR		31.6	31.6	$\mu\text{V/V}$
		90	90	dB
Maximum Output Voltage, (See Figs. 16,22)	V_{OM}^+	3	3	V
	V_{OM}^-	0.3	0.3	
Maximum Output Current: Source,	I_{OM}^+	20	20	mA
	Sink	I_{OM}^-	1	
Slew Rate (See Fig. 6)		7	7	V/ μs
Gain-Bandwidth Product, (See Fig. 5)	f_T	4.5	4.5	MHz
Supply Current, (See Fig. 7)	I^+	4	4	mA
Device Dissipation,	P_D	20	20	mW

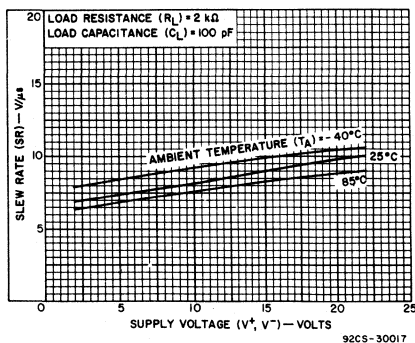


Fig. 6 — Slew rate as a function of supply voltage and temperature.

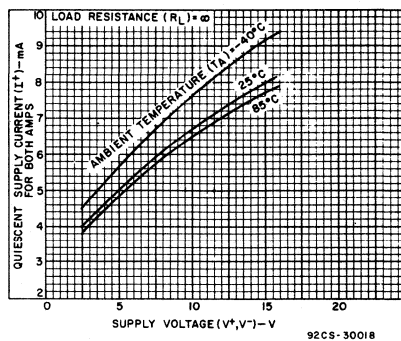


Fig. 7 — Quiescent supply current as a function of supply voltage and temperature.

Operational Amplifiers

CA3240, CA3240A Types

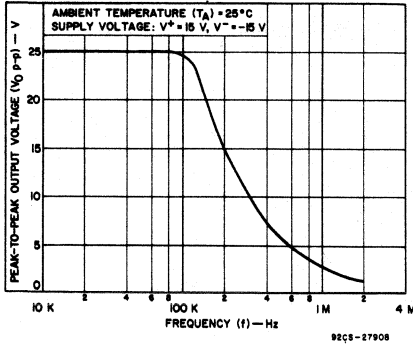


Fig. 8 — Maximum output voltage swing as a function of frequency.

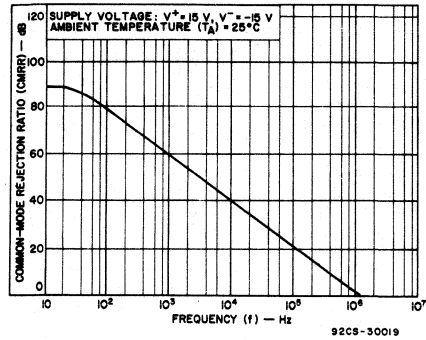


Fig. 9 — Common-mode rejection ratio as a function of frequency.

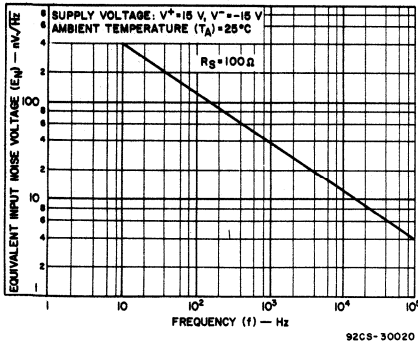


Fig. 10 — Equivalent input noise voltage as a function of frequency.

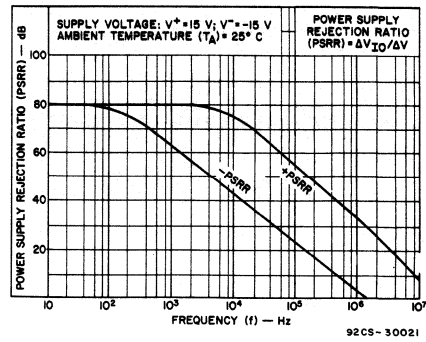


Fig. 11 — Power supply rejection ratio as a function of frequency.

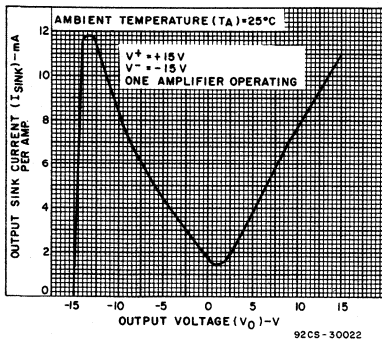


Fig. 12 — Output sink current as a function of output voltage.

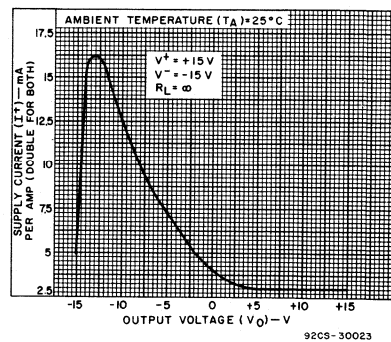


Fig. 13 — Supply current as a function of output voltage.

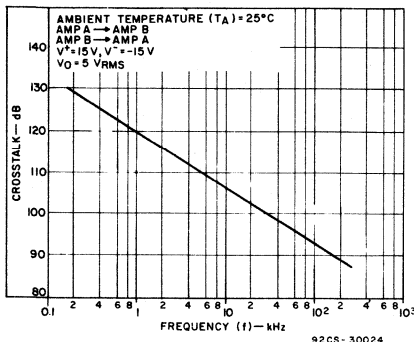


Fig. 14 — Crosstalk as a function of frequency.

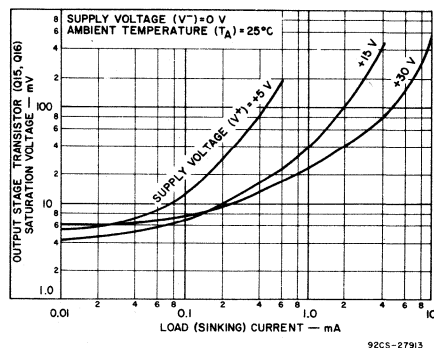


Fig. 15 — Voltage across output transistors Q15 and Q16 as a function of load current.

Linear Integrated Circuits

CA3240, CA3240A Types

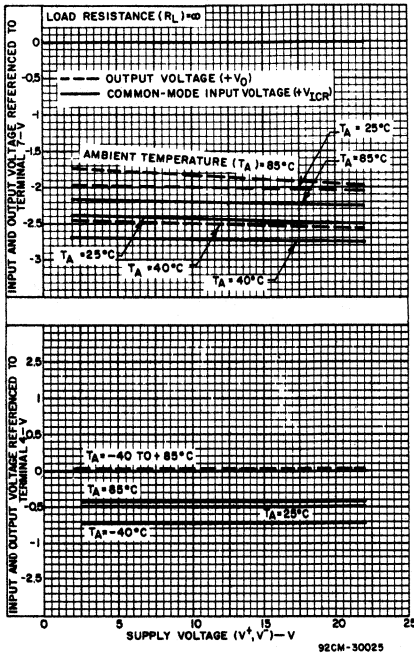


Fig. 16 - Output-voltage-swing capability and common-mode input-voltage range as a function of supply voltage and temperature.

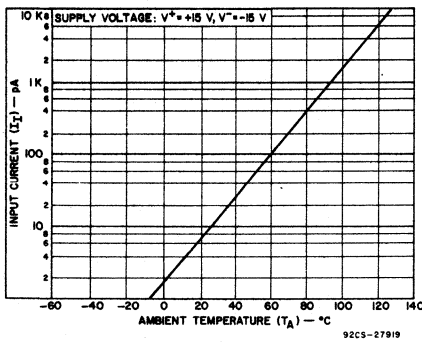


Fig. 18 - Input current as a function of ambient temperature.

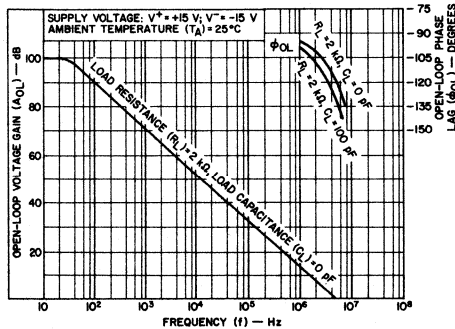


Fig. 19 - Open-loop voltage gain and phase lag as a function of frequency.

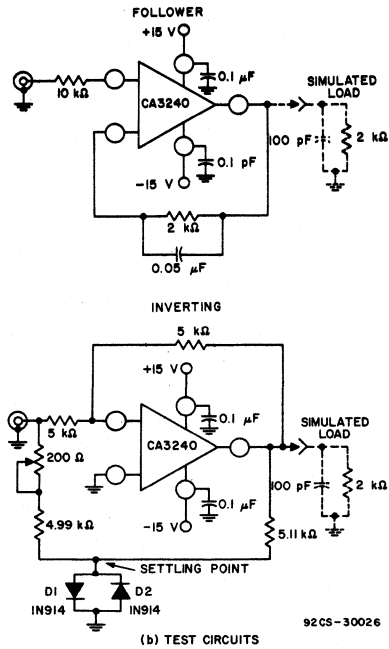
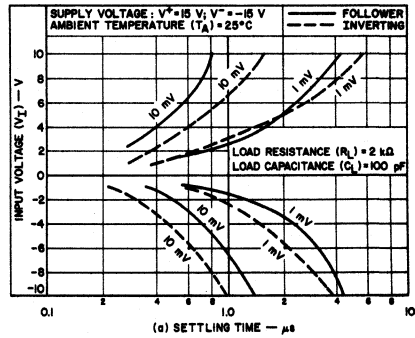
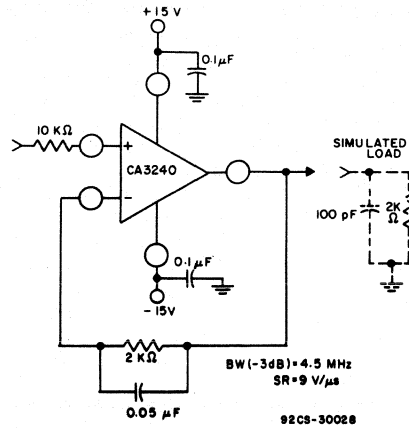


Fig. 17 - Input voltage as a function of settling time.

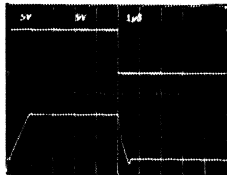
Operational Amplifiers

CA3240, CA3240A Types



TOP TRACE : INPUT
(50 mV/DIV ; 200 ns/DIV.)
BOTTOM TRACE : OUTPUT
(50 mV/DIV ; 200 ns/DIV.)

(a) SMALL SIGNAL RESPONSE

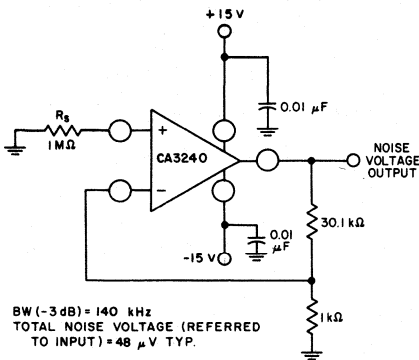


TOP TRACE : INPUT
(5 V/DIV ; 1 μs/DIV.)
BOTTOM TRACE : OUTPUT
(5 V/DIV ; 1 ns/DIV.)

(b) LARGE SIGNAL RESPONSE

92CS-30029

Fig. 20 — Split-supply voltage-follower test circuit and associated waveforms.



92CS-30027

Fig. 21 — Test-circuit amplifier (30-dB gain) used for wideband noise measurement.

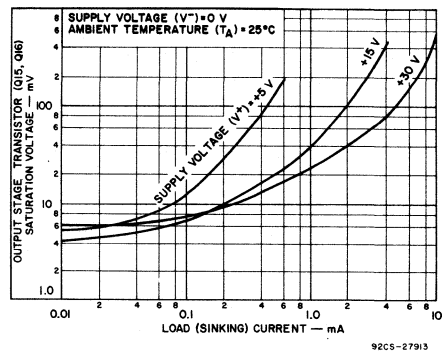


Fig. 22 — Voltage across output transistors Q15 and Q16 as a function of load current.

CA3240, CA3240A Types

APPLICATIONS CONSIDERATIONS

Output Circuit Considerations

Fig. 22 shows output current-sinking capabilities of the CA3240 at various supply voltages. Output voltage swing to the negative supply rail permits this device to operate both power transistors and thyristors directly without the need for level-shifting circuitry usually associated with the 741 series of operational amplifiers.

Fig. 23 shows some typical configurations. Note that a series resistor, R_L , is used in both cases to limit the drive available to the driven device. Moreover, it is recommended that a series diode and shunt diode be used at the thyristor input to prevent large negative transient surges that can appear at the gate of thyristors, from damaging the integrated circuit.

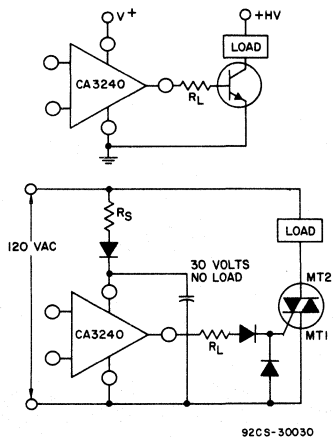


Fig. 23 — Methods of utilizing the $V_{CE(sat)}$ sinking-current capability of the CA3240 series.

Input Circuit Considerations

As indicated by the typical VICR, this device will accept inputs as low as 0.5 V below V^- . However, a series current-limiting resistor is recommended to limit the maximum input terminal current to less than 1 mA to prevent damage to the input protection circuitry.

Moreover, some current-limiting resistance should be provided between the inverting input and the output when the CA3240 is used as a unity-gain voltage follower. This resistance prevents the possibility of extremely large input-signal transients from forcing a signal through the input-protection network and directly driving the internal constant-current source which could result in positive feedback via the output terminal. A 3.9-k Ω resistor is sufficient.

The typical input current is in the order of 10 pA when the inputs are centered at nominal device dissipation. As the output supplies

load current, device dissipation will increase, raising the chip temperature and resulting in increased input current. Fig. 24 shows typical input-terminal current versus ambient temperature for the CA3240.

It is well known that MOS/FET devices can exhibit slight changes in characteristics (for example, small changes in input offset voltage) due to the application of large differential input voltages that are sustained over long periods at elevated temperatures.

Both applied voltage and temperature accelerate these changes. The process is reversible and offset voltage shifts of the opposite polarity reverse the offset. In typical linear applications, where the differential voltage is small and symmetrical, these incremental changes are of about the same magnitude as those encountered in an operational amplifier employing a bipolar transistor input stage.

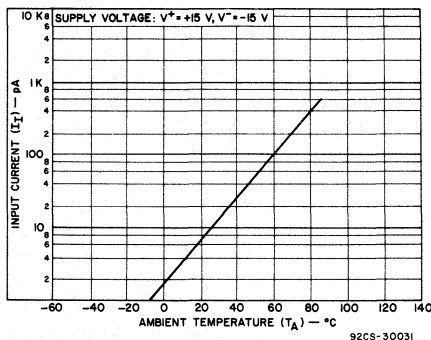


Fig. 24 — Input current as a function of ambient temperature.

Offset-Voltage Nulling

The input-offset voltage of the CA3240AE1 and CA3240E1 can be nulled by connecting a 10-k Ω potentiometer between Terminals 3 and 14 or 5 and 8 and returning its wiper arm to Terminal 4, see Fig. 25a. This technique, however, gives more adjustment range than required and therefore, a considerable portion of the potentiometer rotation is not fully utilized. Typical values of series resistors that may be placed at either end of the potentiometer, see Fig. 25b, to optimize its utilization range are given in the table "Electrical Characteristics For Design Guidance" shown in this bulletin.

An alternate system is shown in Fig. 25c. This circuit uses only one additional resistor of approximately the value shown in the table. For potentiometers, in which the resistance does not drop to zero ohms at either end of rotation, a value of resistance 10% lower than the values shown in the table should be used.

Operational Amplifiers

CA3240, CA3240A Types

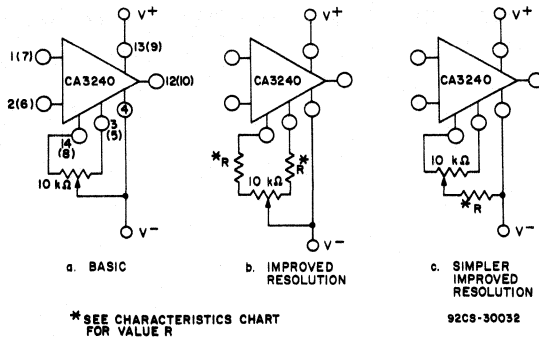


Fig. 25 - Three offset-voltage nulling methods.
(CA3240AE1, CA3240E1 only.)

TYPICAL APPLICATIONS

On/Off Touch Switch

The on/off touch switch shown in Fig. 26 uses the CA3240E to sense small currents flowing between two contact points on a touch plate consisting of a PC board metalization "grid". When the "on" plate is touched, current flows between the two halves of the grid causing a positive shift in the output voltage (Term. 7) of the CA3240E. These positive transitions are fed into the CA3059, which is used as a latching circuit and zero-crossing triac driver. When a positive pulse occurs at Terminal 7 of the CA3240E,

the triac is turned on and held on by the CA3059 and its associated positive feedback circuitry (51-kΩ resistor and 36-kΩ/42-kΩ voltage divider). When the positive pulse occurs at Terminal 1 (CA3240E), the triac is turned off and held off in a similar manner. Note that power for the CA3240E is supplied by the CA3059 internal power supply.

The advantage of using the CA3240E in this circuit is that it can sense the small currents associated with skin conduction while allowing sufficiently high circuit impedance to provide protection against electrical shock.

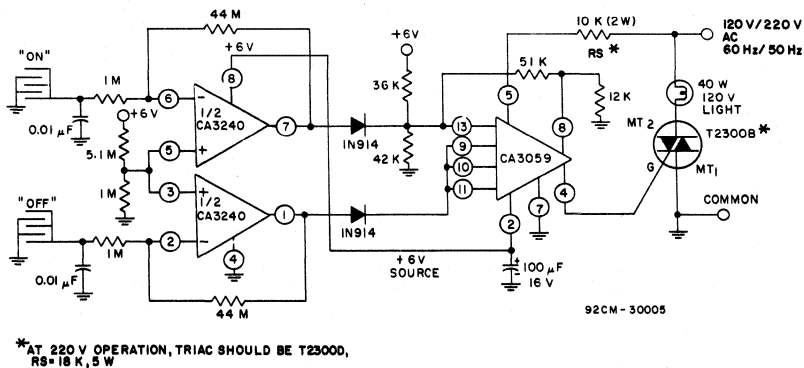


Fig. 26 - On/off touch switch.

Linear Integrated Circuits

CA3240, CA3240A Types

Dual Level Detector (window comparator)

Fig. 27 illustrates a simple dual liquid level detector using the CA3240E as the sensing amplifier. This circuit operates on the principle that most liquids contain enough ions in solution to sustain a small amount of current flow between two electrodes submersed in the liquid. The current, induced by an 0.5-V potential applied between two halves of a

PC board grid, is converted to a voltage level by the CA3240E in a circuit similar to that of the on/off touch switch shown in Fig. 26. The changes in voltage for both the upper and lower level sensors are processed by the CA3140 to activate an LED whenever the liquid level is above the upper sensor or below the lower sensor.

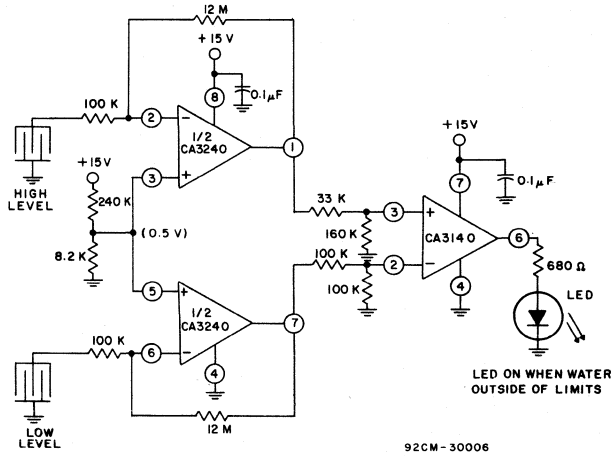


Fig. 27 — Dual level detector.

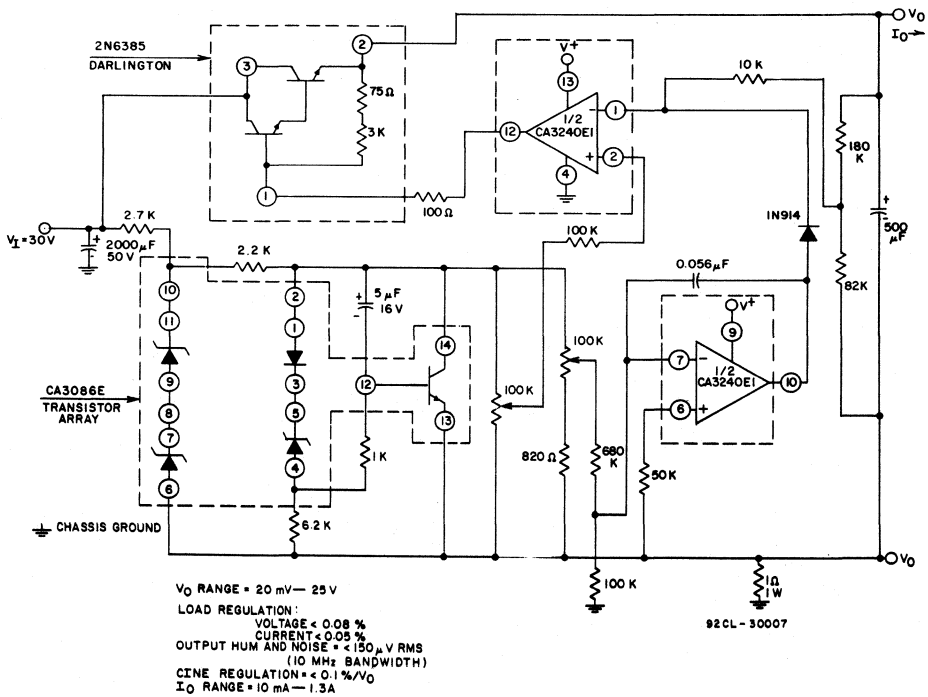


Fig. 28 — Constant-voltage/constant-current power supply.

CA3240, CA3240A Types

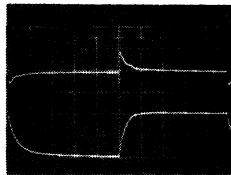
Constant-Voltage/Constant-Current Power Supply

The constant-voltage/constant-current power supply shown in Fig. 28 uses the CA3240E as a voltage-error and current-sensing amplifier. The CA3240E is ideal for this application because its input common-mode voltage-range includes ground, allowing the supply to adjust from 20 mV to 25 V without requiring an additional negative input voltage. Also, the ground reference capability of the CA3240E allows it to sense the voltage across

29 shows the transient response of the supply during a 100-mA to 1-A load transition.

Precision Differential Amplifier

Fig. 30 shows the CA3240E in the classical precision differential amplifier circuit. The CA3240E is ideally suited for biomedical applications because of its extremely high input impedance. To insure patient safety, an extremely high electrode series resistance is required to limit any current that might



TRANSIENT RESPONSE

TOP TRACE : OUTPUT VOLTAGE
(500 mV/cm AND 5 μ s/cm)
BOTTOM TRACE : COLLECTOR OF LOAD
SWITCHING TRANSISTOR
LOAD = 100 mA TO 1A
(5 V/cm AND 5 μ s/cm)

92CS-30034

Fig. 29 - Transient response.

the 1- Ω current-sensing resistor in the negative output lead of the power supply. The CA3086 transistor array functions as a reference for both constant-voltage and constant-current limiting. The 2N6385 power Darlington is used as the pass element and may be required to dissipate as much as 40 W. Fig.

result in patient discomfort in the event of a fault condition. In this case, 10-M Ω resistors have been used to limit the current to less than 2 μ A without affecting the performance of the circuit. Fig. 31 shows a typical electrocardiogram waveform obtained with this circuit.

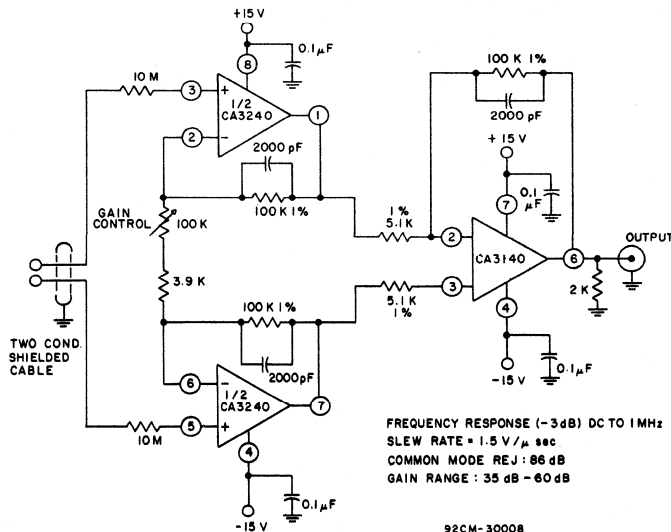
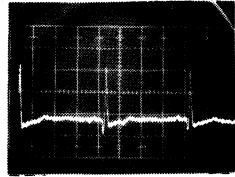


Fig. 30 - Precision differential amplifier.

Linear Integrated Circuits

CA3240, CA3240A Types



TYPICAL ELECTROCARDIOGRAM WAVEFORM

VERTICAL : 1.0 mV/DIV.
(AMPLIFIER GAIN = 100 X)
(SCOPE SENSITIVITY = 0.1V/DIV.)
HORIZONTAL : > 0.2 SEC/DIV (UNCAL)

92CS-30033

Fig. 31 — Typical electrocardiogram waveform.

Differential Light Detector

In the circuit shown in Fig. 32, the CA3240E converts the current from two photo diodes to voltage, and applies 1 V of reverse bias to the diodes. The voltages from the CA3240E outputs are subtracted in the second stage

(CA3140) so that only the difference is amplified. In this manner, the circuit can be used over a wide range of ambient light conditions without circuit component adjustment. Also, when used with a light source, the circuit will not be sensitive to changes in light level as the source ages.

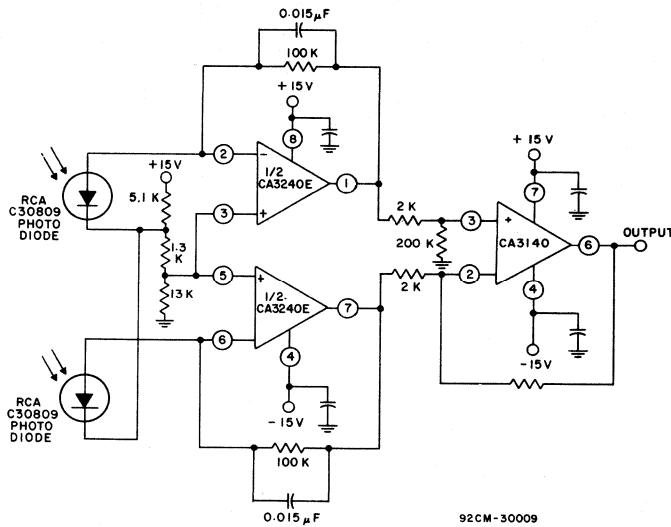
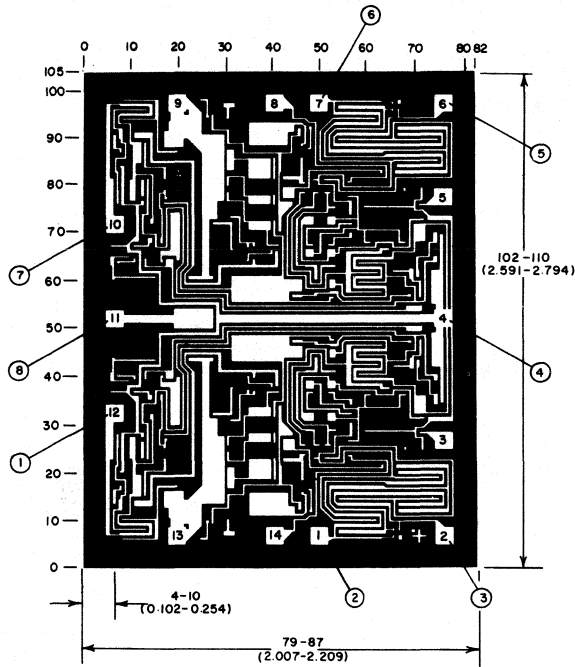


Fig. 32 — Differential light detector.

Operational Amplifiers

CA3240, CA3240A Types

CA3240H Dimensions and Pad Layout



NOTE: NOS. IN PADS ARE FOR 14-LEAD DIP
 NOS. OUTSIDE OF CHIP ARE FOR 8-LEAD DIP
 92CM-30035

The photographs and dimensions represent a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch).

CA3260, CA3260A, CA3260B Types



BiMOS Operational Amplifiers

With MOS/FET Input, COS/MOS Output

FEATURES:

- Dual version of the CA3160
 - MOS/FET input stage provides:
 - very high $Z_i = 1.5 \text{ T}\Omega$ ($1.5 \times 10^{12}\Omega$) typ.
 - very low $I_i = 5 \text{ pA}$ typ. at 15-V operation
 - $= 2 \text{ pA}$ typ. at 5-V operation
 - Common-mode input-voltage range includes negative supply rail; input terminals can be swung 0.5 V below negative supply rail
 - COS/MOS output stage permits signal swing to either (or both) supply rails
- } Ideal for single-supply applications

The RCA-CA3260T, CA3260S, CA3260E; CA3260AT, CA3260AS, CA3260AE; and CA3260BT, CA3260BS are integrated-circuit operational amplifiers that combine the advantages of both COS/MOS and bipolar transistors on a monolithic chip. The CA3260 series circuits are dual versions of the popular CA3160 series.

Gate-protected p-channel MOS/FET (PMOS) transistors are used in the input circuit to provide very-high-input impedance, very-low-input current, and exceptional speed performance. The use of PMOS field-effect transistors in the input stage results in common-mode input-voltage capability down to 0.5 volt below the negative-supply terminal, an important attribute in single-supply applications.

A complementary-symmetry MOS (COS/MOS) transistor-pair, capable of swinging the output voltage to within 10 millivolts of either supply-voltage terminal (at very high values of load impedance), is employed as the output circuit.

The CA3260-series circuits operate at supply voltages ranging from 4 to 16 volts, or ± 2 to ± 8 volts when using split supplies.

The CA3260 series is supplied in standard 8-lead TO-5-style packages (T suffix) and 8-lead dual-in-line formed-lead TO-5 style "DIL-CAN" packages (S suffix). The CA3260 is available in chip form (H suffix).

The CA3260A and CA3260 are also available in the 8-lead dual-in-line plastic package (Mini-DIP E suffix). All types operate over the full military-temperature range of -55°C to $+125^\circ\text{C}$. The CA3260B is intended for applications requiring premium-grade specifications. The CA3260A offers superior input characteristics over those of the CA3260.

- Low V_{IO} : 2 mV max. (CA3260B)
- Wide BW: 4 MHz typ. (unity-gain crossover)
- High SR: 10 V/ μs typ. (unity-gain follower)
- High output current (I_O): 20 mA typ.
- High A_{OL} : 320,000 (110 dB) typ.
- Internal phase compensation for unity gain.
- Same pin-out as CA1458, CA1558

APPLICATIONS:

- Ground-referenced single-supply amplifiers
- Fast sample-and-hold amplifiers
- Long-duration timers/monostables
- Ideal interface with digital COS/MOS
- High-input-impedance wideband amplifiers
- Voltage followers
(e.g., follower for single-supply D/A converter)
- Voltage regulators
(permits control of output voltage down to zero volts)
- Wien-Bridge oscillators
- Voltage-controlled oscillators
- Photo-diode sensor amplifiers

CA3260, CA3260A, CA3260B Types

ELECTRICAL CHARACTERISTICS for Each Amplifier at $T_A=25^\circ\text{C}$,
 $V^+=15\text{ V}$, $V^-=0\text{ V}$ (Unless otherwise specified)

CHARACTERISTIC	LIMITS									UNITS
	CA3260B (T,S)			CA3260A (T,S,E)			CA3260 (T,S,E)			
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage, $ V_{IO} $, $V^\pm=\pm 7.5\text{ V}$	—	0.8	2	—	2	5	—	6	15	mV
Input Offset Current, $ I_{IO} $, $V^\pm=\pm 7.5\text{ V}$	—	0.5	10	—	0.5	20	—	0.5	30	pA
Input Current, I_I $V^\pm=\pm 7.5\text{ V}$	—	5	20	—	5	30	—	5	50	pA
Large-Signal Voltage Gain, A _{OL} $V_O=10\text{ V}_{p-p}$, $R_L=10\text{ k}\Omega$	100 k	320 k	—	50 k	320 k	—	50 k	320 k	—	V/V
	100	110	—	94	110	—	94	110	—	dB
Common-Mode Rejection Ratio, CMRR	86	100	—	80	95	—	70	90	—	dB
Common-Mode Input Voltage Range, V_{ICR}	0	0.5 to 12	10	0	0.5 to 12	10	0	0.5 to 12	10	V
Power-Supply Rejection Ratio, $\Delta V_{IO}/\Delta V^\pm$ $V^\pm=\pm 7.5\text{ V}$	—	32	100	—	32	150	—	32	320	$\mu\text{V}/\text{V}$
Maximum Output Voltage: At $R_L=10\text{ k}\Omega$	V_{OM}^+	11	13.3	—	11	13.3	—	11	13.3	V
	V_{OM}	—	0.002	0.01	—	0.002	0.01	—	0.002	
	V_{OM}^+	14.99	15	—	14.99	15	—	14.99	15	
	V_{OM}	—	0	0.01	—	0	0.01	—	0	
Maximum Output Current, I_{OM}^+ (Source) @ $V_O=7.5\text{ V}$	12	22	45	12	22	45	12	22	45	mA
	I_{OM} (Sink) @ $V_O=7.5\text{ V}$	12	20	45	12	20	45	12	20	
Total Supply Current, I^+ $R_L=\infty$ $V_O(\text{Ampli.A})=V_O$ (Ampli.B)=7.5 V	—	9	15.5	—	9	15.5	—	9	15.5	mA
	V_O (Ampli.A)= V_O (Ampli.B)=0 V	—	1.2	3	—	1.2	3	—	1.2	
	V_O (Ampli.A)=0 V V_O (Ampli.B)=7.5 V	—	5	8.5	—	5	8.5	—	5	
Input Offset Voltage Temp.Drift, $\Delta V_{IO}/\Delta T$	—	5	—	—	6	—	—	8	—	$\mu\text{V}/^\circ\text{C}$
Crosstalk $f=1\text{ kHz}$	—	120	—	—	120	—	—	120	—	dB

Linear Integrated Circuits

CA3260, CA3260A, CA3260B Types

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE
(Between V^+ and V^- Terminals)..... 16 V
DIFFERENTIAL-MODE
INPUT VOLTAGE..... ± 8 V
COMMON-MODE DC
INPUT VOLTAGE..... ($V^+ + 8$ V) to ($V^- - 0.5$ V)
INPUT-TERMINAL CURRENT 1 mA
DEVICE DISSIPATION:
WITHOUT HEAT SINK —
UP TO 55°C 630 mW
ABOVE 55°C ... Derate linearly 6.67 mW/°C

WITH HEAT SINK —
UP TO 90°C 1 W
ABOVE 90°C ... Derate linearly 16.7 mW/°C
TEMPERATURE RANGE:
OPERATING (All Types) -55 to +125°C
STORAGE (All Types) -65 to +150°C
OUTPUT SHORT-CIRCUIT
DURATION* INDEFINITE
LEAD TEMPERATURE
(DURING SOLDERING):
At distance 1/16 \pm 1/32 in.
(1.59 \pm 0.79 mm) from case
for 10 s max. +265°C

*Short circuit may be applied to ground or to either supply.

TYPICAL VALUES INTENDED ONLY FOR DESIGN GUIDANCE

CHARACTERISTIC	TEST CONDITIONS	CA3260 (T, S)	CA3260 (T, S, E)	CA3260 (T, S, E)	UNITS
$V^+ = +7.5$ V, $V^- = -7.5$ V, $T_A = 25^\circ$ C (Unless Otherwise Specified)					
Input Resistance, R_I		1.5	1.5	1.5	$T\Omega$
Input Capacitance, C_I	f=1 MHz	4.3	4.3	4.3	pF
Unity Gain Crossover Frequency, f_T		4	4	4	MHz
Slew Rate, SR		10	10	10	V/ μ s
Transient Response:	$C_L = 25$ pF $R_L = 2$ k Ω (Voltage Follower)				
Rise Time, t_r		0.09	0.09	0.09	μ s
Overshoot		10	10	10	%
Settling Time (4 V_{p-p} Input to < 0.1%)		1.8	1.8	1.8	μ s
$V^+ = 5$ V, $V^- = 0$ V, $T_A = 25^\circ$ C (Unless Otherwise Specified)					
Input Offset Voltage, V_{IO}		1	2	6	mV
Input Offset Current, I_{IO}		0.1	0.1	0.1	pA
Input Current, I_I		2	2	2	pA
Common-Mode Rejection Ratio, CMRR		80	70	60	dB
Large-Signal Voltage Gain, A_{OL}	$V_O = 4$ V_{p-p} $R_L = 20$ k Ω	100 k 100	100 k 100	100 k 100	V/V dB
Common-Mode Input Voltage Range, V_{ICR}		0 to 2.5	0 to 2.5	0 to 2.5	V
Supply Current, I^+	$V_O = 5$ V, $R_L = \infty$	1	1	1	mA
	$V_O = 2.5$ V, $R_L = \infty$	1.2	1.2	1.2	
Power Supply Rejection Ratio, $\Delta V_{IO} / \Delta V^+$		200	200	200	μ V/V

Operational Amplifiers

CA3260, CA3260A, CA3260B Types

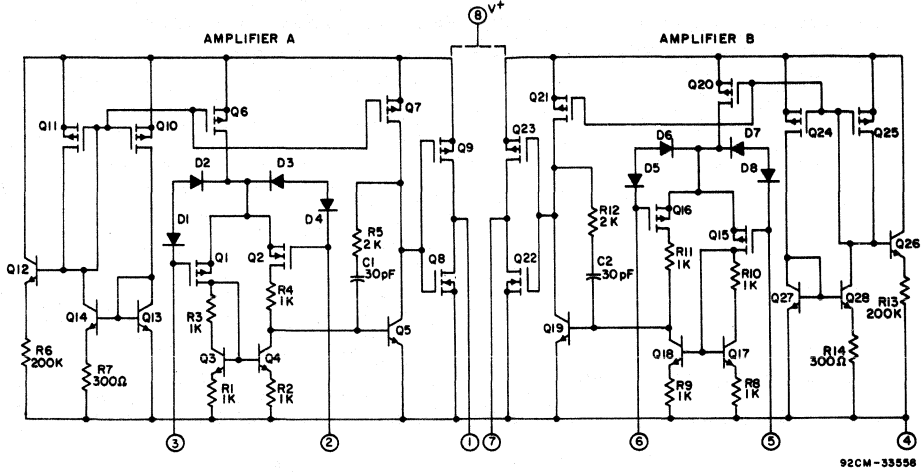
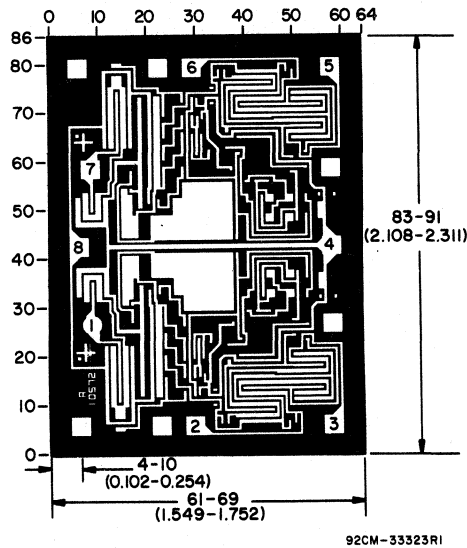


Fig. 1 - Schematic diagram of CA3260 series.



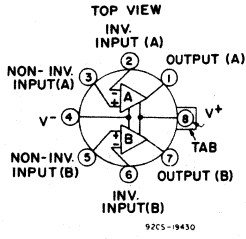
Dimensions and pad layout for CA3260H.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

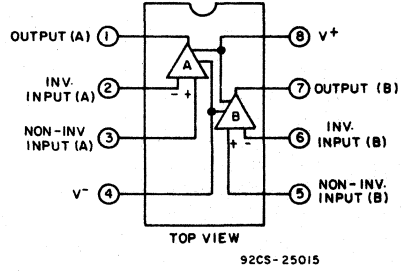
The layout represents a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

Linear Integrated Circuits

CA3260, CA3260A, CA3260B Types



S and T Suffixes
Pin compatible with the
industry-standard 1458



E Suffix
Pin compatible with the
industry-standard 1458

Fig. 2 - Functional diagrams for the CA3260 Series.

CA3094, CA3094A, CA3094B Types

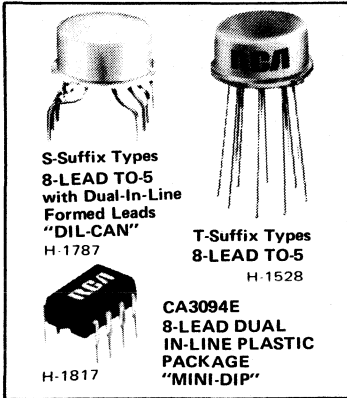
Programmable Power Switch/Amplifier

For Control & General-Purpose Applications

CA3094T,S,E: For Operation Up to 24 Volts

CA3094AT,S,E: For Operation Up to 36 Volts

CA3094BT,S: For Operation Up to 44 Volts



Features:

- Designed for single or dual power supply
- Programmable: strobing, gating, squelching, AGC capabilities
- Can deliver 3 watts (avg.) or 10 W (peak) to external load (in switching mode)
- High-power, single-ended class A amplifier will deliver power output of 0.6 watt [1.6 W device dissipation]
- Total harmonic distortion [THD] @ 0.6 W in class A operation - 1.4% typ.
- High current-handling capability - 100 mA (avg.), 300 mA (peak)
- Sensitivity controlled by varying bias current
- Output: "sink" or "drive" capability

Applications:

- Error-signal detector: temperature control with thermistor sensor; speed control for shunt wound dc motor
- Over-current, over-voltage, over-temperature protectors
- Dual-tracking power supply with RCA-CA3085
- Wide-frequency-range oscillator
- Analog timer
- Level detector
- Alarm systems
- Voltage follower
- Ramp-voltage generator
- High-power comparator
- Ground-fault interrupter [GFI] circuits

The CA3094 is a differential-input power-control switch/amplifier with auxiliary circuit features for ease of programmability. For example, an error or unbalance signal can be amplified by the CA3094 to provide an on-off signal or proportional-control output signal up to 100 mA. This signal is sufficient to directly drive high-current thyristors, relays, dc loads, or power transistors. The CA3094 has the generic characteristics of the RCA-CA3080 operational amplifier directly coupled to an integral Darlington power transistor capable of sinking or driving currents up to 100 mA.

The gain of the differential input stage is proportional to the amplifier bias current (I_{ABC}), permitting programmable variation of the integrated circuit sensitivity with either digital and/or analog programming signals. For example, at an I_{ABC} of 100 μ A, a one-millivolt change at the input will change the output from 0 to 100 mA (typical).

The CA3094 is intended for operation up to 24 volts and is especially useful for timing circuits, in automotive equipment, and in other applications where operation up to 24 volts is a primary design requirement (see Figs. 28, 29 and 30 in Applications Section). The CA3094A and CA3094B are like the CA3094 but are intended for operation up to 36 and 44 volts, respectively (single or dual supply).

These types are available in 8-lead TO-5 style packages with standard leads ("T" suffix) and with dual-in-line

formed leads "DIL-CAN" ("S" suffix). Type CA3094 is also available in an 8-lead dual-in-line plastic package "MINI-DIP" ("E" suffix), and in chip form ("H" suffix).

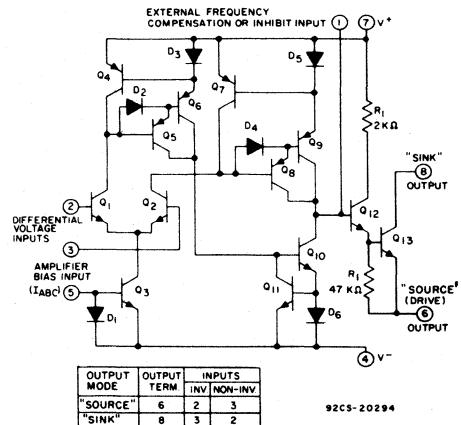


Fig. 1 — Schematic diagram of CA3094.

Linear Integrated Circuits

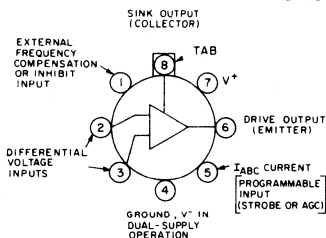
CA3094, CA3094A, CA3094B Types

MAXIMUM RATINGS, Absolute-Maximum Values:

	CA3094	CA3094A	CA3094B	
DC SUPPLY VOLTAGE:				
Dual Supply	± 12 V	± 18 V	± 22 V	V
Single Supply	24 V	36 V	44 V	V
DC DIFFERENTIAL INPUT VOLTAGE (Terminals 2 and 3)	± 5*			V
DC COMMON-MODE INPUT VOLTAGE (Terminals 2 and 3)	Term. 4 ≤ Term. 2 & 3 ≤ Term. 7			
PEAK INPUT SIGNAL CURRENT (Terminals 2 and 3)	± 1			mA
PEAK AMPLIFIER BIAS CURRENT (Terminal 5)	2			mA
OUTPUT CURRENT:				
Peak	300			mA
Average	100			mA
DEVICE DISSIPATION:				
Up to T _A = 55°C:				
Without heat sink	630			mW
With heat sink	1.6			W
Above T _A = 55°C:				
Without heat sink derate linearly	6.67			mW/°C
With heat sink derate linearly	16.7			mW/°C
THERMAL RESISTANCE (Junction to Air)	140			°C/W
AMBIENT TEMPERATURE RANGE:				
Operating	-55 to +125			°C
Storage	-65 to +150			°C
LEAD TEMPERATURE (DURING SOLDERING): At distance 1/16 ± 1/32 in. (1.59 ± 0.79 mm) from case for 10 s max.	+ 300			°C

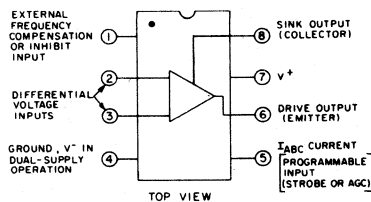
* Exceeding this voltage rating will not damage the device unless the peak input signal current (1 mA) is also exceeded.

FUNCTIONAL DIAGRAMS



NOTE: PIN 4 IS CONNECTED TO CASE
TOP VIEW
92CS-24881

TO-5 Style Package



92CS-24882

Plastic Package

TYPICAL CHARACTERISTICS CURVES

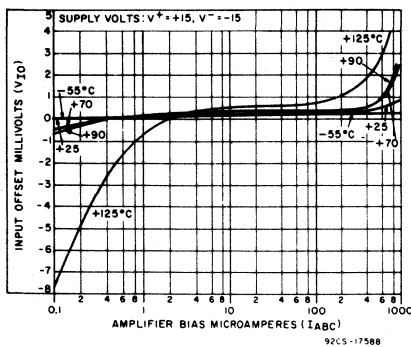


Fig.2 - Input offset voltage vs. amplifier bias current (I_{ABC} , terminal No.5).

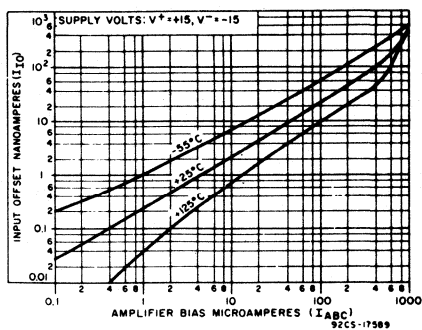


Fig.3 - Input offset current vs. amplifier bias current (I_{ABC} , terminal No.5).

Operational Amplifiers

CA3094, CA3094A, CA3094B Types

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$ For Equipment Design

CHARACTERISTIC	TEST CONDITIONS		LIMITS			UNITS
	Single Supply $V^+ = 30\text{ V}$ Dual Supply $V^+ = 15\text{ V}$, $V^- = -15\text{ V}$ $I_{ABC} = 100\ \mu\text{A}$ Unless Otherwise Specified		Min.	Typ.	Max.	
INPUT PARAMETERS						
Input Offset Voltage V_{IO}	$T_A = 25^\circ\text{C}$		—	0.4	5	mV
	$T_A = 0\text{ to }70^\circ\text{C}$		—	—	7	mV
Input-Offset-Voltage Change $ \Delta V_{IO} $	Change in V_{IO} Between $I_{ABC} = 100\ \mu\text{A}$ and $I_{ABC} = 5\ \mu\text{A}$		—	1	8	mV
Input Offset Current I_{IO}	$T_A = 25^\circ\text{C}$		—	0.02	0.2	μA
	$T_A = 0\text{ to }70^\circ\text{C}$		—	—	0.3	μA
Input Bias Current I_I	$T_A = 25^\circ\text{C}$		—	0.2	0.50	μA
	$T_A = 0\text{ to }70^\circ\text{C}$		—	—	0.70	μA
Device Dissipation P_D	$I_{out} = 0$		8	10	12	mW
Common-Mode Rejection Ratio CMRR			70	110	—	dB
Common-Mode Input— Voltage Range V_{ICR}	$V^+ = 30\text{ V}$ High		27	28.8	—	V
	$V^+ = 30\text{ V}$ Low		1.0	0.5	—	V
	$V^+ = 15\text{ V}$		+12	+13.8	—	V
	$V^- = 15\text{ V}$		-14	-14.5	—	V
Unity Gain-Bandwidth	$I_C = 7.5\text{ mA}$ $V_{CE} = 15\text{ V}$ $I_{ABC} = 500\ \mu\text{A}$		—	30	—	MHz
Open-Loop Bandwidth At -3 dB Point BW_{OL}	$I_C = 7.5\text{ mA}$ $V_{CE} = 15\text{ V}$ $I_{ABC} = 500\ \mu\text{A}$		—	4	—	kHz
Total Harmonic Distortion (Class A Operation) THD	$P_D = 220\text{ mW}$		—	0.4	—	%
	$P_D = 600\text{ mW}$		—	1.4	—	%
Amplifier Bias Voltage V_{ABC} (Terminal (No.5 to Terminal No.4))			—	0.68	—	V
Input Offset Voltage Temperature Coefficient $\Delta V_{IO}/\Delta T$			—	4	—	$\mu\text{V}/^\circ\text{C}$
Power-Supply Rejection $\Delta V_{IO}/\Delta V$			—	15	150	$\mu\text{V}/\text{V}$
1/F Noise Voltage E_N	$f = 10\text{ Hz}$ $I_{ABC} = 50\ \mu\text{A}$		—	18	—	$\eta\sqrt{\text{Hz}}$
1/F Noise Current I_N	$f = 10\text{ Hz}$ $I_{ABC} = 50\ \mu\text{A}$		—	1.8	—	$\text{pA}/\sqrt{\text{Hz}}$
Differential Input Resistance R_I	$I_{ABC} = 20\ \mu\text{A}$		0.50	1	—	M Ω
Differential Input Capacitance C_I	$f = 1\text{ MHz}$ $V^+ = 30\text{ V}$		—	2.6	—	pF

Linear Integrated Circuits

CA3094, CA3094A, CA3094B Types

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$ For Equipment Design

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
	Single Supply $V^+ = 30\text{ V}$ Dual Supply $V^+ = 15\text{ V}$, $V^- = -15\text{ V}$ $I_{ABC} = 100\ \mu\text{A}$ Unless Otherwise Specified	Min.	Typ.	Max.	
OUTPUT PARAMETERS (Differential Input Voltage = 1V)					
Peak Output Voltage: (Terminal No. 6) With Q13 "ON" V^+OM With Q13 "OFF" V^-OM	$V^+ = 30\text{ V}$ $R_L = 2\text{ k}\Omega$ to ground	26 —	27 0.01	— 0.05	V V
Peak Output Voltage: (Terminal No. 6) Positive V^+OM Negative V^-OM	$V^+ = +15\text{ V}$, $V^- = -15\text{ V}$ $R_L = 2\text{ k}\Omega$ to -15 V	+11 —	+12 -14.99	— -14.95	V V
Peak Output Voltage: (Terminal No. 8) With Q13 "ON" V^+OM With Q13 "OFF" V^-OM	$V^+ = 30\text{ V}$ $R_L = 2\text{ k}\Omega$ to 30 V	29.95 —	29.99 0.040	— —	V V
Peak Output Voltage: (Terminal No. 8) Positive V^+OM Negative V^-OM	$V^+ = 15\text{ V}$, $V^- = -15\text{ V}$ $R_L = 2\text{ k}\Omega$ to $+15\text{ V}$	+14.95 —	+14.99 14.96	— —	V V
Collector-to-Emitter Saturation Voltage (Terminal No. 8) $V_{CE(sat)}$	$V^+ = 30\text{ V}$ $I_C = 50\text{ mA}$ Terminal No. 6 grounded	—	0.17	0.80	V
Output Leakage Current (Terminal No. 6 to Terminal No. 4)	$V^+ = 30\text{ V}$	—	2	10	μA
Composite Small-Signal Current Transfer Ratio (Beta) (Q_{12} and Q_{13}) h_{fe}	$V^+ = 30\text{ V}$ $V_{CE} = 5\text{ V}$ $I_C = 50\text{ mA}$	16,000	100,000	—	
Output Capacitance: Terminal No. 6 C_O Terminal No. 8	$f = 1\text{ MHz}$ All Remaining Terminals Tied to Terminal No. 4	— —	5.5 17	— —	pF pF
TRANSFER PARAMETERS					
Voltage Gain A	$V^+ = 30\text{ V}$ $I_{ABC} = 100\ \mu\text{A}$ $\Delta V_{out} = 20\text{ V}$ $R_L = 2\text{ k}\Omega$	20,000	100,000	—	V/V
		86	100	—	dB
Forward Transconductance To Terminal No. 1 g_m		1650	2200	2750	μmhos
Slew Rate: Open Loop: Positive Slope Negative Slope	$I_{ABC} = 500\ \mu\text{A}$ $R_L = 2\text{ k}\Omega$	— —	500 50	— —	V/ μs V/ μs
Unity Gain (Non-Inverting, Compensated)	$I_{ABC} = 500\ \mu\text{A}$ $R_L = 2\text{ k}\Omega$	—	0.7	—	V/ μs

CA3094, CA3094A, CA3094B Types

TYPICAL CHARACTERISTICS CURVES (Cont'd)

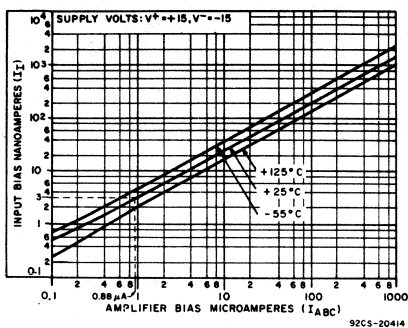


Fig. 4 - Input bias current vs. amplifier bias current (I_{ABC} , terminal No.5).

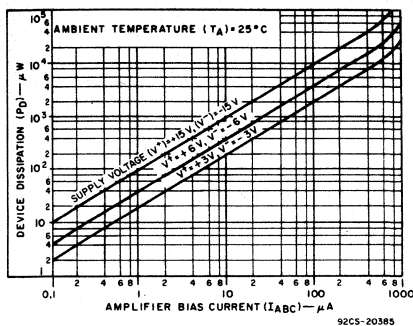


Fig. 5 - Device dissipation vs. amplifier bias current (I_{ABC} , terminal No.5).

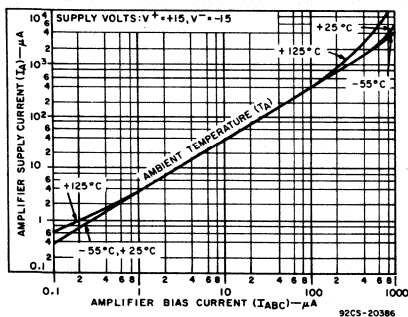


Fig. 6 - Amplifier supply current vs. amplifier bias current (I_{ABC} , terminal No.5).

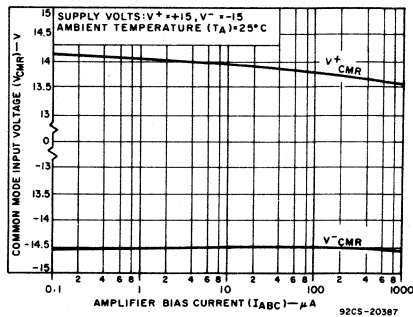


Fig. 7 - Common mode input voltage vs. amplifier bias current (I_{ABC} , terminal No.5).

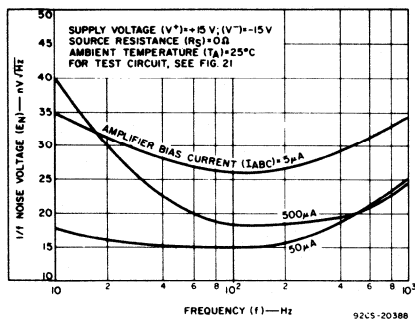


Fig. 8 - $1/f$ Noise voltage vs. frequency.

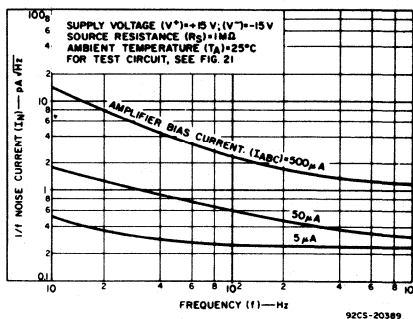


Fig. 9 - $1/f$ Noise current vs. frequency.

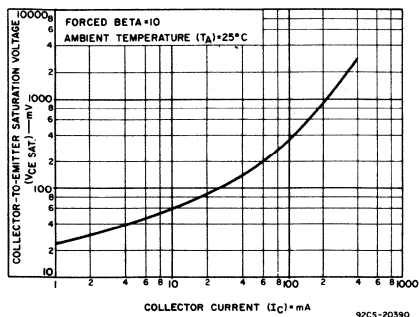


Fig. 10 - Collector-emitter saturation voltage vs. collector current of output transistor Q_{13} .

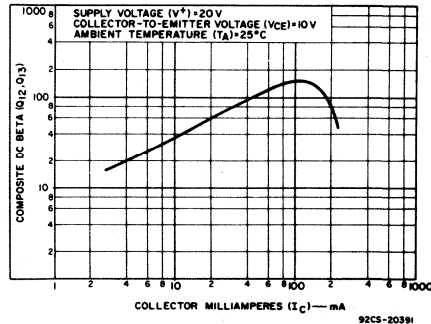


Fig. 11 - Composite dc beta vs. collector current of Darlington-connected output transistors Q_{12} , Q_{13} .

CA3094, CA3094A, CA3094B Types

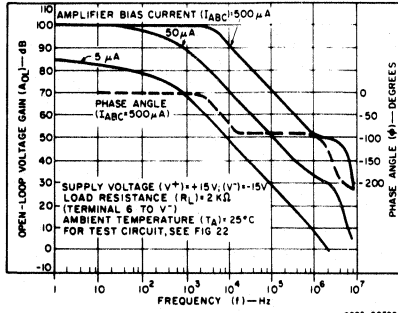


Fig. 12 — Open-loop voltage gain vs. frequency.

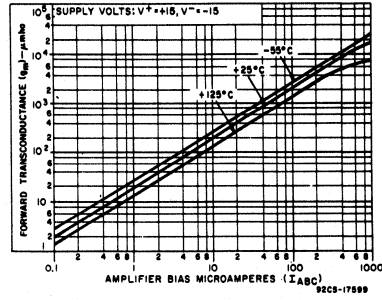


Fig. 13 — Forward transconductance vs amplifier bias current.

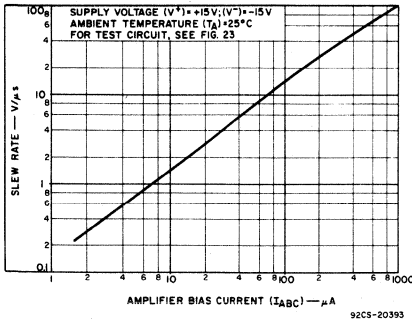


Fig. 14 — Slew rate vs amplifier bias current.

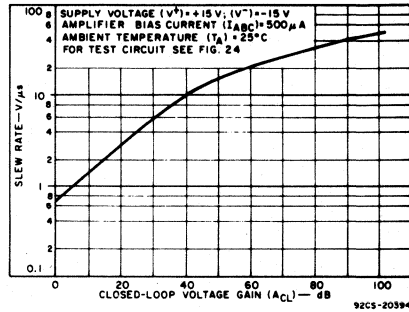


Fig. 15 — Slew rate vs closed-loop voltage gain.

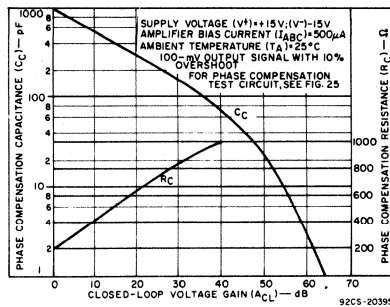


Fig. 16 — Phase compensation capacitance and resistance vs closed-loop voltage gain.

OPERATING CONSIDERATIONS

The "Sink" Output (terminal No.8) and the "Drive" Output (terminal No.6) of the CA3094 are not inherently current (or power) limited. Therefore, if a load is connected between terminal No.6 and terminal No.4 (V^- or ground), it is important to connect a current-limiting resistor between terminal 8 and terminal No.7 (V^+) to protect transistor Q13 under shorted load conditions. Similarly, if a load is connected between terminal No.8 and terminal No.7, the current-limiting resistor should be connected between terminal No.6 and terminal No.4 or ground. In circuit applications where the emitter of the output transistor is not connected to the most negative potential in the system, it is recommended that a 100-ohm current-limiting resistor be inserted between terminal No.7 and the V^+ supply.

TEST CIRCUITS

1/f Noise Measurement Circuit

When using the CA3094, A, or B audio amplifier circuits, it is frequently necessary to consider the noise performance of the device. Noise measurements are made in the circuit shown in Fig.21. This circuit is a 30-dB, non-inverting amplifier with emitter-follower output and phase compensation from terminal No.2 to ground. Source resistors (R_s) are set to 0. Ω or 1 M Ω for E noise and 1 noise measurements, respectively. These measurements are made at frequencies of 10, Hz, 100 Hz, and 1 kHz with a 1-Hz measurement bandwidth. Typical values for 1/f noise at 10 Hz and 50 μA I_{ABC} are $E_n = 18 \text{ nV}/\sqrt{\text{HZ}}$ and $I_n = 1.8 \text{ pA}/\sqrt{\text{HZ}}$.

CA3094, CA3094A, CA3094B Types

TEST CIRCUITS

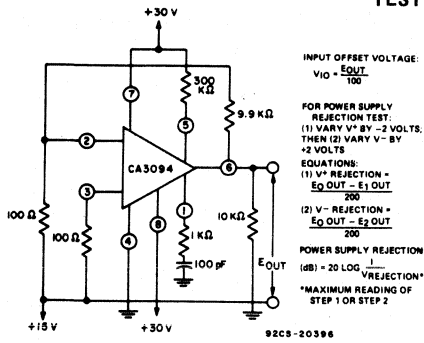


Fig. 17 - Input offset voltage and power-supply rejection test circuit.

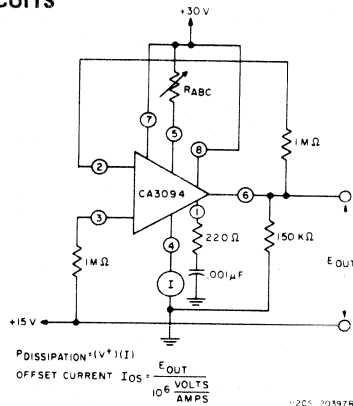


Fig. 18 - Input offset current test circuit.

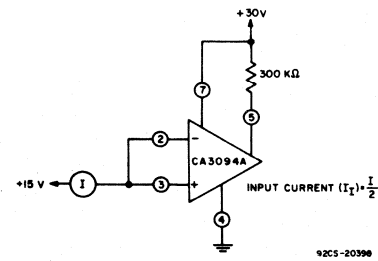


Fig. 19 - Input bias current test circuit.

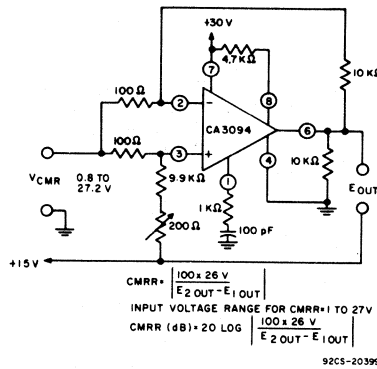


Fig. 20 - Common-mode range and rejection ratio test circuit.

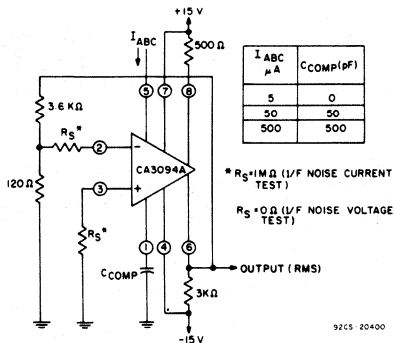


Fig. 21 - 1/f noise test circuit.

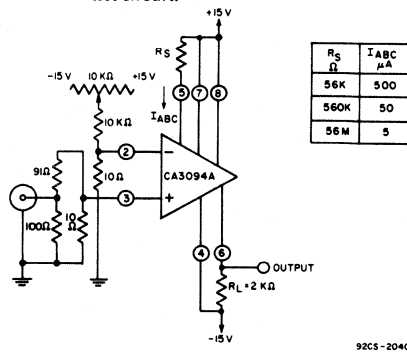


Fig. 22 - Open-loop gain vs frequency test circuit.

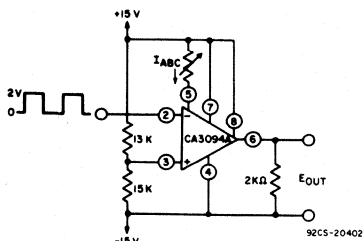


Fig. 23 - Open-loop slew rate vs I_{ABC} test circuit.

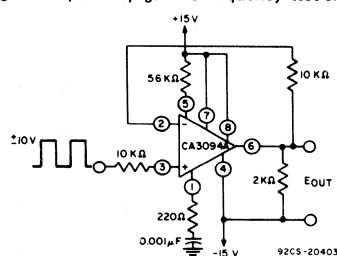


Fig. 24 - Slew rate vs. non-inverting unity gain test circuit.

CA3094, CA3094A, CA3094B Types

TEST CIRCUITS (Cont'd)

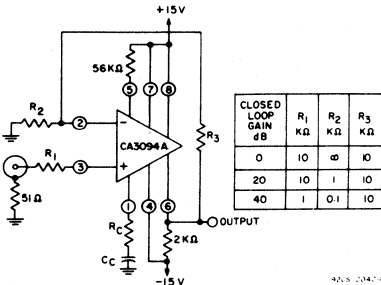


Fig.25 - Phase compensation test circuit.

TYPICAL APPLICATIONS

For Additional Application Information, refer to Application Note ICAN-6048 "Some Applications of a Programmable Power/Switch Amplifier IC".

Design Considerations

The selection of the optimum amplifier bias current (I_{ABC}) depends on -

1. The Desired Sensitivity - the higher the I_{ABC}, the higher the sensitivity - i.e., a greater-drive current capability at the output for a specific voltage change at the input.

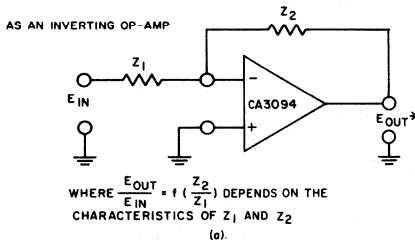
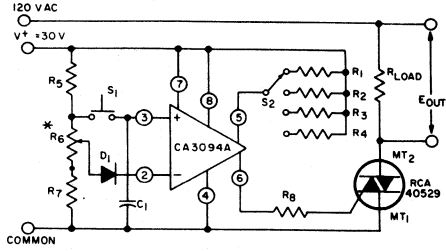
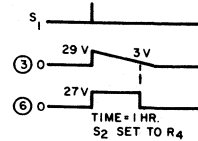


Fig.27 - Application of the CA3094: (a) as an inverting op-amp, and (b) in a non-inverting mode, as a follower.



- C₁ = 0.5 μF
- D₁ = 1N914
- R₁ = 0.51 MΩ = 3 MIN.
- R₂ = 5.1 MΩ = 30 MIN.
- R₃ = 22 MΩ = 2 HRS.
- R₄ = 44 MΩ = 4 HRS.
- R₅ = 1.5 KΩ
- R₆ = 50 KΩ
- R₇ = 5.1 KΩ
- R₈ = 1.5 KΩ

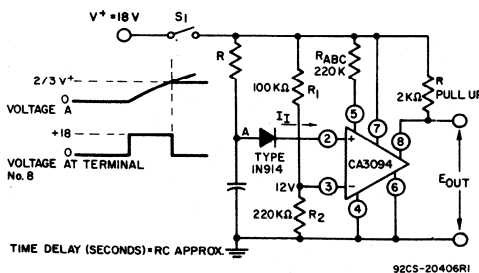
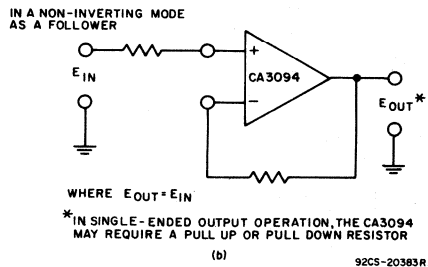


* POTENTIOMETER REQUIRED FOR INITIAL TIME SET TO PERMIT DEVICE INTERCONNECTING TIME VARIATION WITH TEMPERATURE < 0.3 %/°C.

Fig.26 - Presetable analog timer.

2. Required Input Resistance - the lower the I_{ABC}, the higher the input resistance. If the desired sensitivity and required input resistance are not known and are to be experimentally determined, or the anticipated equipment design is sufficiently flexible to tolerate a wide range of these parameters, it is recommended that the equipment designer begin his calculations with an I_{ABC} of 100 μA, since the CA3094 is characterized at this value of amplifier bias current.

The CA3094 is extremely versatile and can be used in a wide variety of applications.



Problem: To calculate the maximum value of R required to switch a 100-mA output current comparator

Given: $I_{ABC} = 5 \mu A, R_{ABC} = 3.6 M\Omega \approx \frac{18 V}{5 \mu A}$

$I_1 = 500 nA @ I_{ABC} = 100 \mu A$ (from Fig.4)
 $I_1 = 5 \mu A$ can be determined by drawing a line on Fig.4 through $I_{ABC} = 100 \mu A$ and $I_B = 500 nA$ parallel to the typical $T_A = 25^\circ C$ curve.

Then: $I_1 = 33 nA @ I_{ABC} = 5 \mu A$

$R_{max} = \frac{18 - 12 \text{ volts}}{33 nA} = 180 M\Omega @ T_A = 25^\circ C$

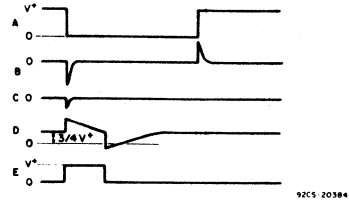
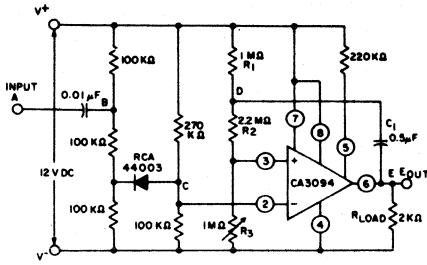
$R_{max} = 180 M\Omega \times 2/3 = 120 M\Omega @ T_A = -55^\circ C$

* Ratio of I_1 at $T_A = +25^\circ C$ to I_1 at $T_A = -55^\circ C$ for any given value of I_{ABC}.

Fig.28 - RC timer.

CA3094, CA3094A, CA3094B Types

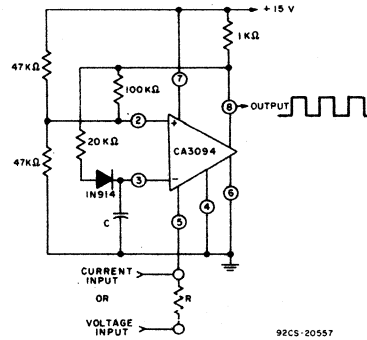
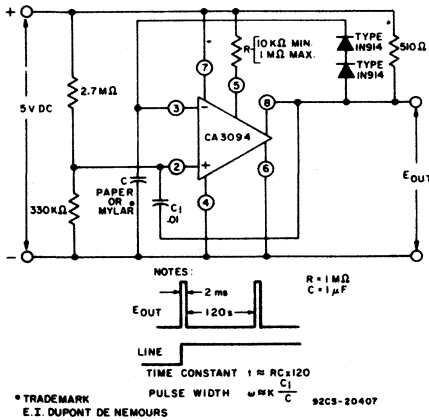
TYPICAL APPLICATIONS (Cont'd)



On a negative-going transient at input (A), a negative pulse at C will turn "on" the CA3094, and the output (E) will go from a low to a high level.

At the end of the time constant determined by C_1 , R_1 , R_2 , R_3 , the CA3094 will return to the "off" state and the output will be pulled low by R_{LOAD} . This condition will be independent of the interval when input A returns to a high level.

Fig.29 - RC timer triggered by external negative pulse.



* TRADEMARK E. I. DUPONT DE NEMOURS 92CS-20407

92CS-20557

Fig.30 - Free-running pulse generator.

Fig.31 - Current or voltage-controlled oscillator.

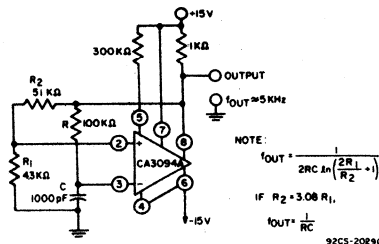
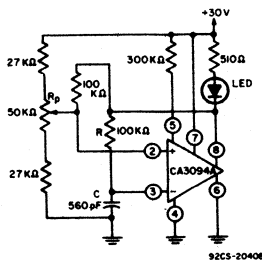


Fig.32 - Single-supply astable multivibrator.

Fig.33 - Dual-supply astable multivibrator.

Linear Integrated Circuits

CA3094, CA3094A, CA3094B Types

TYPICAL APPLICATIONS (Cont'd)

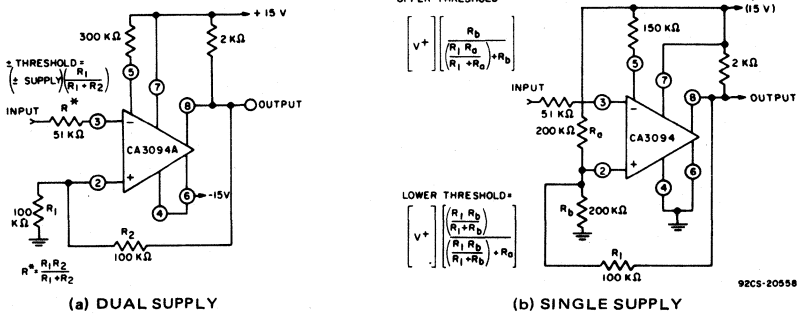


Fig. 34 - Comparators (threshold detectors) - dual- and single-supply types.

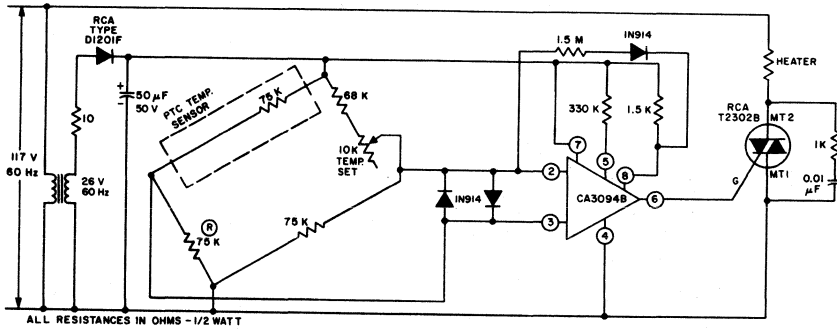


Fig. 35 - Temperature controller.

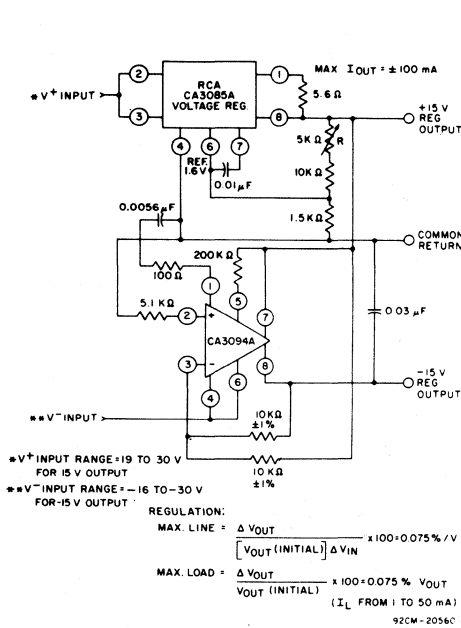


Fig. 36 - Dual-voltage tracking regulator.

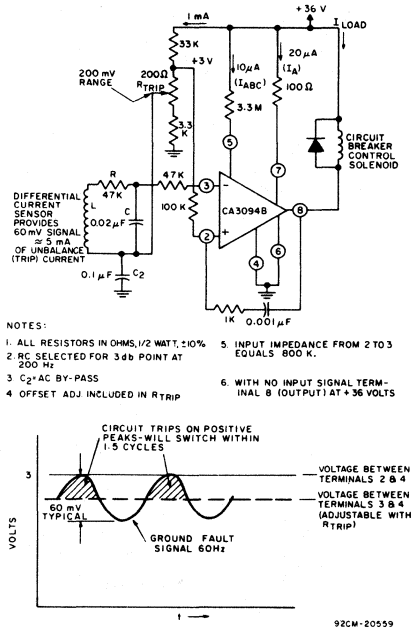
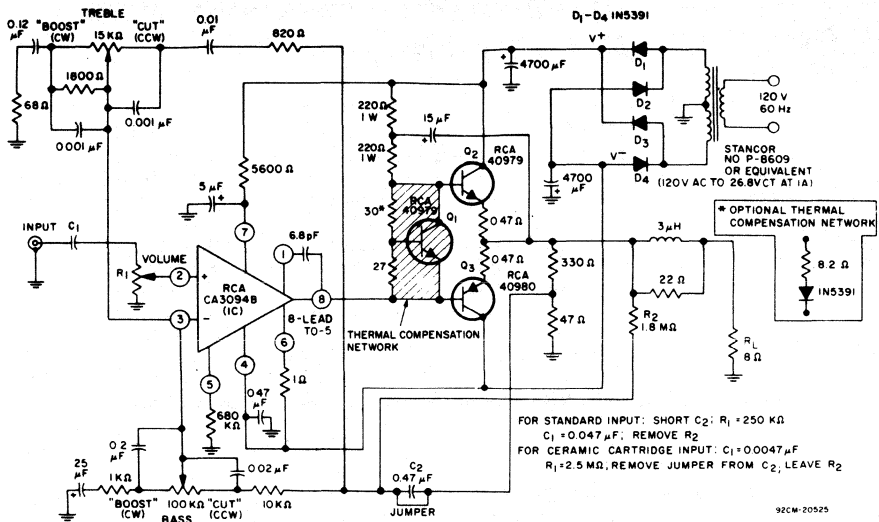


Fig. 37 - Ground fault interrupter (GFI) and waveform pertinent to ground fault detector.

CA3094, CA3094A, CA3094B Types

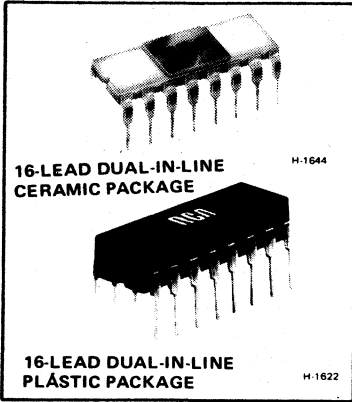


TYPICAL PERFORMANCE DATA
 For 12-W Audio Amplifier Circuit

Power Output (8Ω load, Tone Control set at "Flat")		
Music (at 5% THD, regulated supply)	15	W
Continuous (at 0.2% IMD, 60 Hz & 2 kHz mixed in a 4:1 ratio, unregulated supply) See Fig. 8 In ICAN-6048	12	W
Total Harmonic Distortion		
At 1 W, unregulated supply	0.05	%
At 12 W, unregulated supply	0.57	%
Voltage Gain	40	dB
Hum and Noise (Below continuous Power Output)	83	dB
Input Resistance	250	kΩ
Tone Control Range	See Fig. 9 In ICAN-6048	

Fig. 38 — 12-watt amplifier circuit featuring true complementary-symmetry output stage with CA3094 in driver stage.

CA3060, CA3060A Types



Operational Transconductance Amplifier Arrays

Features:

- Low power consumption – as low as 100 μ W per amplifier
- Independent biasing for each amplifier
- High forward transconductance
- Programmable range of input characteristics
- Low input bias and input offset current
- High input and output impedance
- No effect on device under output short-circuit conditions
- Zener diode bias regulator

Applications:

- For low power conventional operational amplifier applications
- Active filters
- Comparators
- Gytrators
- Mixers
- Modulators
- Multiplexers
- Multipliers
- Strobing and gating functions
- Sample and hold functions

RCA-CA3060AD, CA3060BD, CA3060D, and CA3060E, monolithic integrated circuits, are arrays of three independent Operational Transconductance Amplifiers. This type of amplifier is a new circuit concept that has the generic characteristics of an operational voltage amplifier with the exception that the forward gain characteristic is best described by transconductance rather than voltage gain (open-loop voltage gain is the product of the transconductance and the load resistance, $g_m R_L$). When operated into a suitable load resistor and with provisions for feedback, these amplifiers are well suited for a wide variety of operational-amplifier and related applications. In addition, the extremely high output impedance makes these types particularly well suited for service in active filters.

The three amplifiers in the CA3060 family are identical push-pull Class A types which can be independently biased to achieve a wide range of characteristics for specific application. The electrical characteristics of each amplifier are a function of the amplifier bias current (I_{ABC}). This feature offers the system designer maximum flexibility with regard to output current capability, power consumption, slew rate,

input resistance, input bias current, and input offset current. The linear variation of the parameters with respect to bias and the ability to maintain a constant dc level between input and output of each amplifier also makes the CA3060 suitable for a variety of non-linear applications such as mixers, multipliers, and modulators.

In addition; the types in the CA3060 family incorporate a unique Zener diode regulator system that permits current regulation below supply voltages normally associated with such systems.

Generic applications of the OTA are described in ICAN-6668, Applications of the CA3080 and CA3080A High-Performance Operational Transconductance Amplifiers.

The CA3060AD, CA3060BD, and CA3060D are supplied in a hermetic 16-lead dual-in-line ceramic package which can be operated over the full military temperature range, -55°C to $+125^\circ\text{C}$. The CA3060E is supplied in a 16-lead dual-in-line plastic package and is operational from -40°C to $+85^\circ\text{C}$.

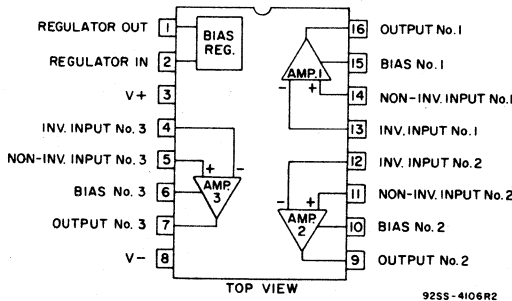


Fig. 1 — Functional block diagram for each type in the CA3060 family.

Operational Amplifiers

CA3060, CA3060A Types

MAXIMUM RATINGS, Absolute Maximum Values at $T_A = 25^\circ\text{C}$

DC Supply Voltage (between V^+ and V^- terminals):	
CA3060AD, CA3060BD, CA3060E	36 V ($\pm 18\text{V}$)
CA3060D	14 V ($\pm 7\text{V}$)
Differential Input Voltage (each amplifier):	
CA3060AD, CA3060BD, CA3060E	$\pm 5\text{V}$
CA3060D	$\pm 5\text{V}$
DC Input Voltage	
	V^+ to V^-
Input Signal Current (each amplifier of each type):	
	$\pm 1\text{ mA}$
Amplifier Bias Current (each amplifier of each type)	
	2 mA
Bias Regulator Input Current	
	-5 mA
Output Short-Circuit Duration*	
	No limitation

Device Dissipation:

Total Package of each type up to $T_A = 75^\circ\text{C}$	490 mW
Above $T_A = 75^\circ\text{C}$	Derate linearly 6.67 mW/ $^\circ\text{C}$

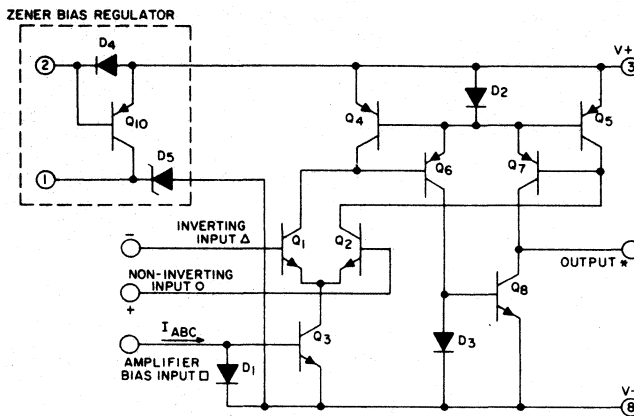
Temperature Range:

Operating —	
CA3060AD, CA3060BD, CA3060D	-55 to +125 $^\circ\text{C}$
CA3060E	-40 to +85 $^\circ\text{C}$
Storage —	
CA3060AD, CA3060BD, CA3060D,	
CA3060E	-65 to +150 $^\circ\text{C}$

Lead Temperature (During Soldering):

At distance 1/16 \pm 1/32 in. (1.59 \pm 0.79 mm)	
from case for 10s max.	+300 $^\circ\text{C}$

*Short circuit may be applied to ground or to either supply.



- Δ INVERTING INPUT OF AMPLIFIERS 1, 2, AND 3 IS ON TERMINAL Nos. 13, 12 AND 4, RESPECTIVELY
- NON-INVERTING INPUT OF AMPLIFIERS 1, 2, AND 3 IS TERMINAL Nos. 14, 11, AND 5, RESPECTIVELY
- * OUTPUT OF AMPLIFIERS 1, 2, AND 3 IS ON TERMINAL Nos. 16, 9, AND 7, RESPECTIVELY
- AMPLIFIER BIAS CURRENT OF AMPLIFIERS 1, 2, AND 3 IS ON TERMINAL Nos. 15, 10, AND 6, RESPECTIVELY

NOTE: A complete schematic diagram of the OTA is shown on Page 6.

92CS-15860RI

Fig.2—Simplified schematic diagram showing bias regulator and one operational transconductance amplifier for each type of the CA3060 family.

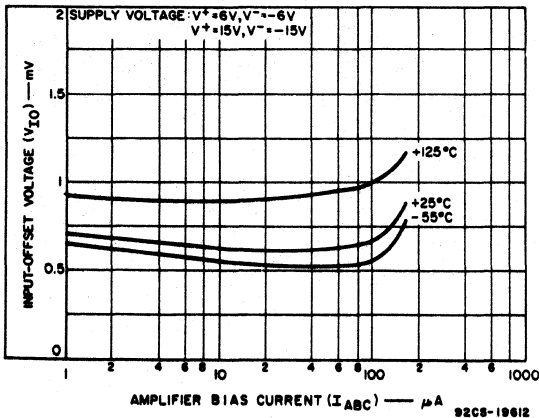


Fig.3—Input offset voltage vs. amplifier bias current.

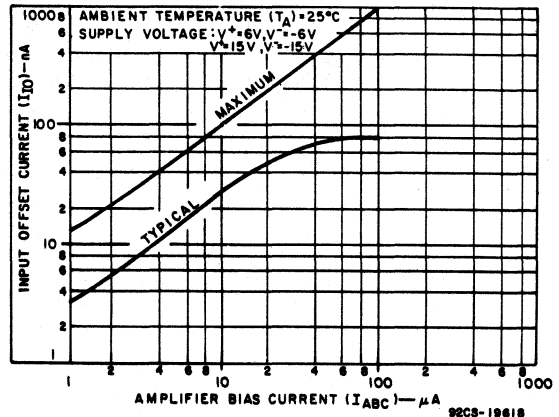


Fig.4—Input offset current vs. amplifier bias current.

Linear Integrated Circuits

CA3060, CA3060A Types

ELECTRICAL CHARACTERISTICS (CA3060D)

For each amplifier at $T_A = 25^\circ\text{C}$, $V^+ = 6\text{ V}$, $V^- = -6\text{ V}$

CHARACTERISTIC	SYMBOL	TYPICAL CHARACTERISTICS CURVES Fig.	LIMITS									UNITS
			Amplifier Bias Current									
			$I_{ABC} = 1\ \mu\text{A}$			$I_{ABC} = 10\ \mu\text{A}$			$I_{ABC} = 100\ \mu\text{A}$			
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
STATIC CHARACTERISTICS												
Input Offset Voltage	V_{IO}	3	-	1	5	-	1	5	-	1	5	mV
Input Offset Current	I_{IO}	4	-	3	14	-	30	100	-	250	1000	nA
Input Bias Current	I_{IB}	5a, b	-	33	70	-	300	550	-	2500	5000	nA
Peak Output Current	I_{OM}	6a, b	1.3	2.3	-	15	26	-	150	240	-	μA
Peak Output Voltage: Positive	V_{OM}^+	7	4.6	5	-	4.5	4.8	-	4.5	4.7	-	V
Negative	V_{OM}^-		5.8	5.95	-	5.8	5.95	-	5.7	5.9	-	
Amplifier Supply Current (each amplifier)	I_A	8a, b	-	8.5	14	-	85	120	-	850	1200	μA
Power Consumption (each amplifier)	P	-	-	0.10	0.17	-	1	1.45	-	10	14.5	mW
Input Offset-Voltage Sensitivity*: Positive	$\Delta V_{IO}/\Delta V^+$	-	-	1.5	120	-	2	120	-	2	120	$\mu\text{V}/\text{V}$
Negative	$\Delta V_{IO}/\Delta V^-$		-	20	120	-	20	120	-	30	120	
Amplifier Bias Voltage*	V_{ABC}	9	-	0.54	-	-	0.60	-	-	0.66	-	V
DYNAMIC CHARACTERISTICS (at 1 kHz unless specified otherwise)												
Forward Transconductance (large signal)	g_{21}	10a, b	0.3	1.55	-	3	18	-	30	102	-	mmho
Common-Mode Rejection Ratio	CMRR	-	70	110	-	70	110	-	70	90	-	dB
Common-Mode Input-Voltage Range	V_{ICR}	-	4.4 to -5.1 min. 4.7 to -5.3 typ.			4.3 to -5 min. 4.6 to -5.2 typ.			4.3 to -5 min. 4.6 to -5.2 typ.			V
Slew Rate (Test ckt., Fig. 13)	SR	-	-	0.1	-	-	1	-	-	8	-	$\text{V}/\mu\text{s}$
Open-Loop (g_{21}) Bandwidth	BW_{OL}	11	-	20	-	-	45	-	-	110	-	kHz
Input Impedance Components:												
Resistance	R_I	12	800	1600	-	90	170	-	10	20	-	$\text{k}\Omega$
Capacitance at 1 MHz	C_I	-	-	2.7	-	-	2.7	-	-	2.7	-	pF
Output Impedance Components:												
Resistance	R_O	14	-	200	-	-	20	-	-	2	-	$\text{M}\Omega$
Capacitance at 1 MHz	C_O	-	-	4.5	-	-	4.5	-	-	4.5	-	pF
ZENER BIAS REGULATOR CHARACTERISTICS (at $T_A = 25^\circ\text{C}$, $I_2 = 0.1\text{ mA}$)												
						MIN.	TYP.	MAX.				
Voltage	V_Z	15	Temp. Coeff. = 3 mV/ $^\circ\text{C}$			6.2	6.7	7.9				V
Impedance	Z_Z	-				200	300					Ω

* Temperature-Coefficient: -2.2 mV/ $^\circ\text{C}$ (at $V_{ABC} = 0.54\text{ V}$, $I_{ABC} = 1\ \mu\text{A}$); -2.1 mV/ $^\circ\text{C}$ (at $V_{ABC} = 0.60\text{ V}$, $I_{ABC} = 10\ \mu\text{A}$); -1.9 mV/ $^\circ\text{C}$ (at $V_{ABC} = 0.66\text{ V}$, $I_{ABC} = 100\ \mu\text{A}$)

■ Conditions for Input Offset Voltage and Supply Sensitivity:

(a) Bias current derived from the regulator with an appropriate resistor connected from terminal No. 1 to the bias terminal on the amplifier under test ...

V^+ is reduced to 5 volts for V^+ sensitivity

V^- is reduced to -5 volts for V^- sensitivity

(b) V^+ sensitivity in $\mu\text{V}/\text{V} = \frac{\text{Voffset} - \text{Voffset for } +5\text{ V and } -6\text{ V supplies}}{1\text{ volt}}$

V^- sensitivity in $\mu\text{V}/\text{V} = \frac{\text{Voffset} - \text{Voffset for } -5\text{ V and } +6\text{ V supplies}}{1\text{ volt}}$

CA3060, CA3060A Types

ELECTRICAL CHARACTERISTICS (CA3060AD, CA3060BD, CA3060E)

For each amplifier at $T_A = 25^\circ\text{C}$, $V^+ = 15\text{ V}$, $V^- = -15\text{ V}$

CHARACTERISTIC	SYMBOL	TYPICAL CHARACTERISTICS CURVE Fig.	LIMITS									UNITS
			Amplifier Bias Current									
			$I_{ABC} = 1\ \mu\text{A}$			$I_{ABC} = 10\ \mu\text{A}$			$I_{ABC} = 100\ \mu\text{A}$			
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
CA3060BD						CA3060AD			CA3060E			
STATIC CHARACTERISTICS												
Input Offset Voltage	V_{IO}	3	—	1	5	—	1	5	—	1	5	mV
Input Offset Current	I_{IO}	4	—	3	14	—	30	100	—	250	1000	nA
Input Bias Current	I_{IB}	5a,b	—	33	70	—	300	550	—	2500	5000	nA
Peak Output Current	I_{OM}	6a,b	1.3	2.3	—	15	26	—	150	240	—	μA
Peak Output Voltage:												
Positive	V_{OM+}	7	12	13.6	—	12	13.6	—	12	13.6	—	V
Negative	V_{OM-}		12	14.7	—	12	14.7	—	12	14.7	—	
Amplifier Supply Current (each amplifier)	I_A	8a,b	—	8.5	14	—	85	120	—	850	1200	μA
Power Consumption (each amplifier)	P_r	—	—	0.26	0.42	—	2.6	3.6	—	26	36	mW
Input Offset-Voltage Sensitivity [■] :												
Positive	$\Delta V_{IO}/\Delta V^+$	—	—	1.5	150	—	2	150	—	2	150	$\mu\text{V}/\text{V}$
Negative	$\Delta V_{IO}/\Delta V^-$		—	20	150	—	20	150	—	30	150	
Amplifier Bias Voltage*	V_{ABC}	9	—	0.54	—	—	0.60	—	—	0.66	—	V
DYNAMIC CHARACTERISTICS (at 1 kHz unless specified otherwise)												
Forward Transconductance (large signal)	g_{21}	10a,b	0.3	1.55	—	3	18	—	30	102	—	mmho
Common-Mode Rejection Ratio	CMRR	—	70	110	—	70	110	—	70	90	—	dB
Common-Mode Input Voltage Range	V_{ICR}	—	+12 to -12 min. +13 to -14 typ.			+12 to -12 min. +13 to -14 typ.			+12 to -12 min. +13 to -14 typ.			V
Slew Rate (Test ckt., Fig. 13)	SR	—	—	0.1	—	—	1	—	—	8	—	$\text{V}/\mu\text{s}$
Open-Loop (g_{21}) Bandwidth	BW_{OL}	11	—	20	—	—	45	—	—	110	—	kHz
Input Impedance Components:												
Resistance	R_i	12	800	1600	—	90	170	—	10	20	—	$\text{k}\Omega$
Capacitance at 1 MHz	C_i	—	—	2.7	—	—	2.7	—	—	2.7	—	pF
Output Impedance Components:												
Resistance	R_o	14	—	200	—	—	20	—	—	2	—	$\text{M}\Omega$
Capacitance at 1 MHz	C_o	—	—	4.5	—	—	4.5	—	—	4.5	—	pF
ZENER BIAS REGULATOR CHARACTERISTICS (at $T_A = 25^\circ\text{C}$, $I_2 = 0.1\text{ mA}$)												
Voltage	V_Z	15	Temp. Coeff. = $3\text{ mV}/^\circ\text{C}$			MIN.	TYP.	MAX.				V
Impedance	Z_Z	—				6.2	6.7	7.9				Ω

* Temperature-Coefficient: $-2.2\text{ mV}/^\circ\text{C}$ (at $V_{ABC} = 0.54\text{ V}$, $I_{ABC} = 1\ \mu\text{A}$); $-2.1\text{ mV}/^\circ\text{C}$ (at $V_{ABC} = 0.60\text{ V}$, $I_{ABC} = 10\ \mu\text{A}$); $-1.9\text{ mV}/^\circ\text{C}$ (at $V_{ABC} = 0.66\text{ V}$, $I_{ABC} = 100\ \mu\text{A}$)

■ Conditions for Input Offset Voltage and Supply Sensitivity:

- (a) Bias current derived from the regulator with an appropriate resistor connected from terminal No. 1 to the bias terminal on the amplifier under test ...

V^+ is reduced to 13 volts for V^+ sensitivity

V^- is reduced to -13 volts for V^- sensitivity

(b) V^+ sensitivity in $\mu\text{V}/\text{V} = \frac{\text{Voffset} - \text{Voffset for } +13\text{ V and } -15\text{ V supplies}}{1\text{ volt}}$

V^- sensitivity in $\mu\text{V}/\text{V} = \frac{\text{Voffset} - \text{Voffset for } -13\text{ V and } +15\text{ V supplies}}{1\text{ volt}}$

CA3060, CA3060A Types

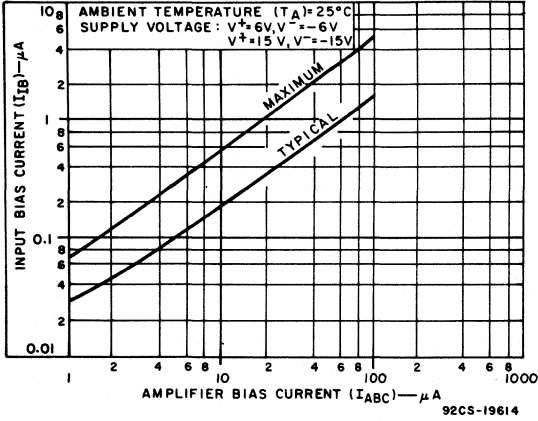


Fig. 5a—Input bias current vs. amplifier bias current

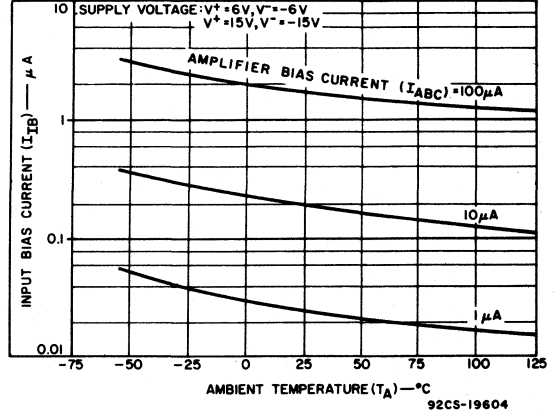


Fig. 5b—Input bias current vs. ambient temperature.

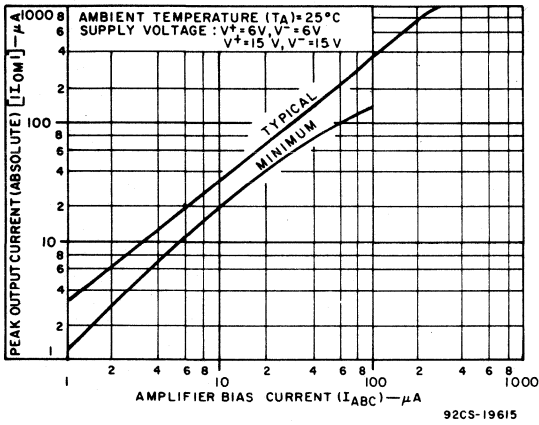


Fig. 6a—Peak output current vs. amplifier bias current.

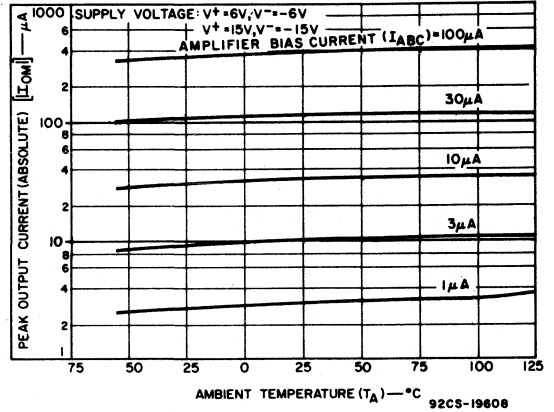


Fig. 6b—Peak output current vs. ambient temperature.

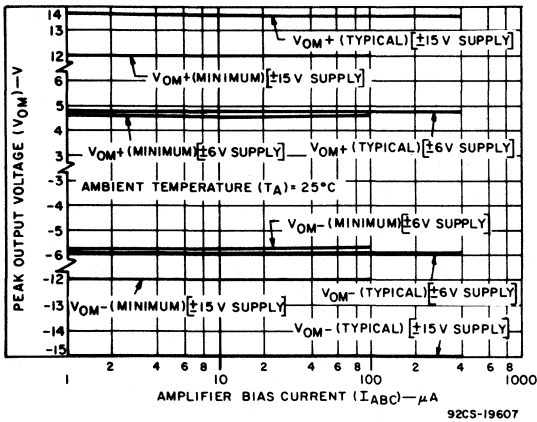


Fig. 7—Peak output voltage vs. amplifier bias current.

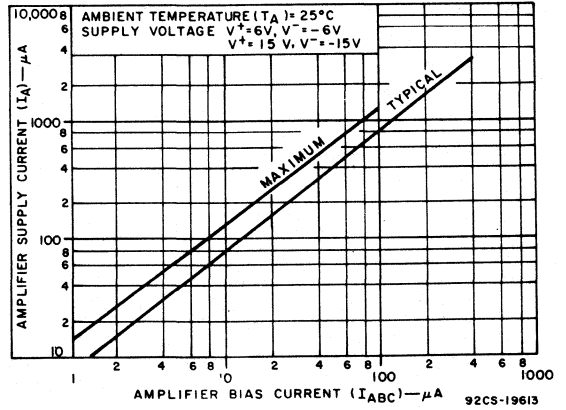


Fig. 8a—Amplifier supply current (each amplifier) vs. amplifier bias current.

CA3060, CA3060A Types

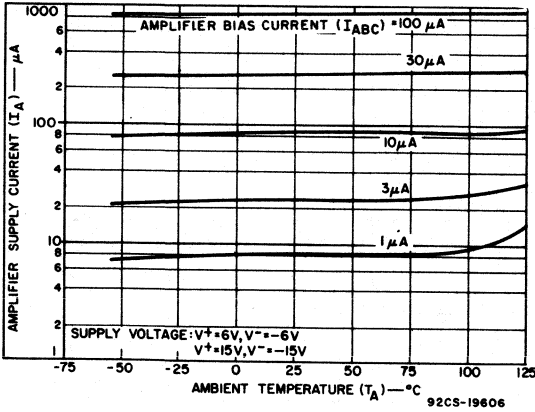


Fig.8b—Amplifier supply current (each amplifier) vs. ambient temperature.

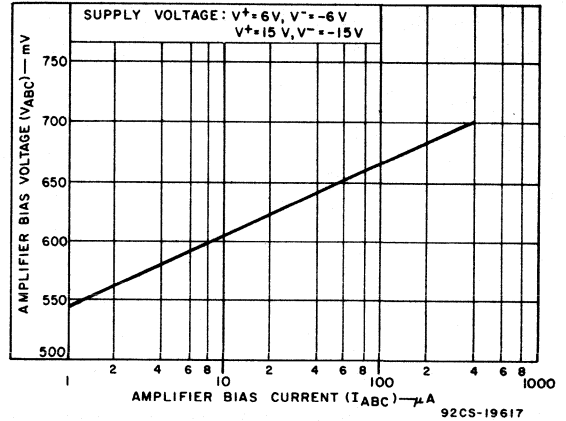


Fig.9—Amplifier bias voltage vs. amplifier bias current.

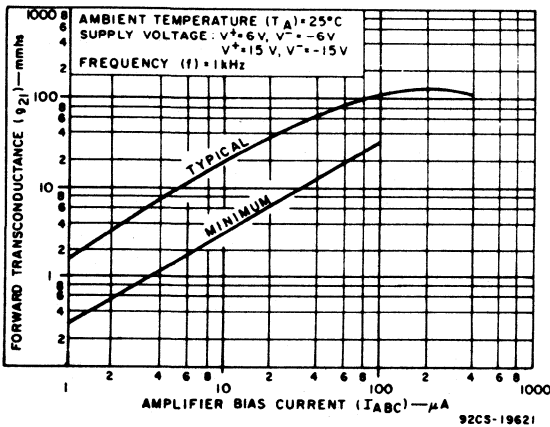


Fig.10a—Forward transconductance vs. amplifier bias current.

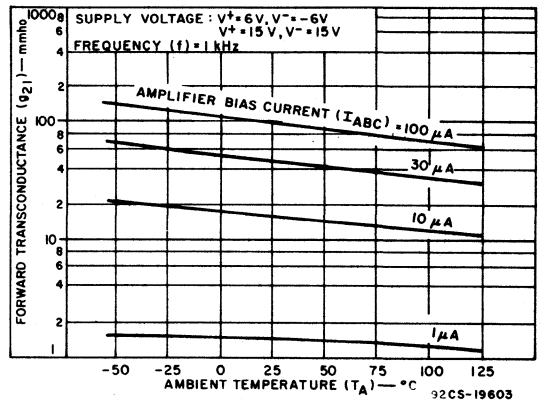


Fig.10b—Forward transconductance vs. ambient temperature.

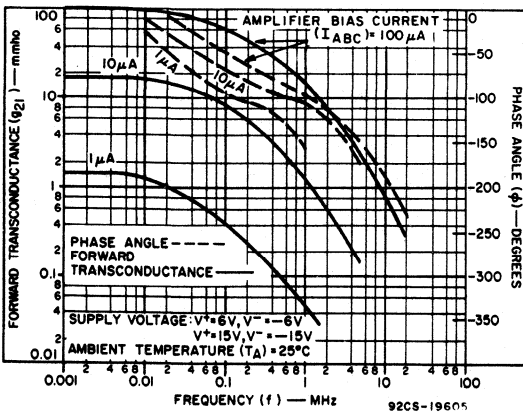


Fig.11—Forward transconductance vs. frequency.

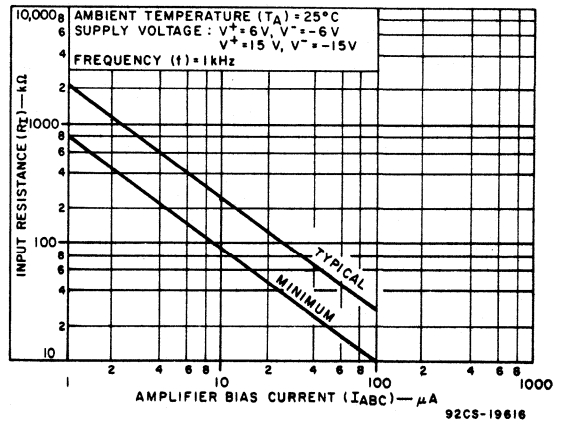
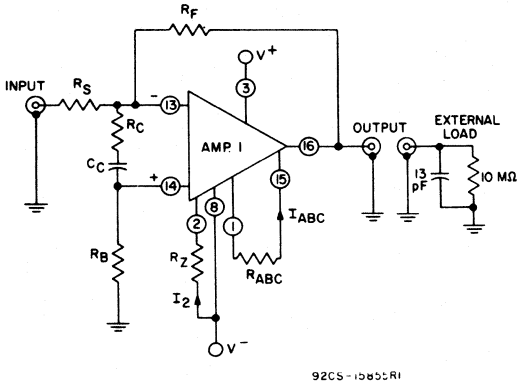


Fig.12—Input resistance vs. amplifier bias current.

Linear Integrated Circuits

CA3060, CA3060A Types



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V_Z is measured between terminals 1 and 8.

V_{ABC} is measured between terminals 15 and 8.

$$R_Z = \frac{[(V^+) - (V^-) - 0.7]}{I_2}, \quad R_{ABC} = \frac{V_Z - V_{ABC}}{I_{ABC}}$$

Supply Voltage: for both ± 6 V and ± 15 V.

TYPICAL SLEW RATE TEST CIRCUIT PARAMETERS

I_{ABC}	SLEW RATE	I_2	R_{ABC}	R_S	R_F	R_B	R_C	C_C
μA	V/ μs	μA	ohms				μF	
100	8	200	62 k	100k	100k	51k	100	0.02
10	1	200	620k	1M	1M	510k	1k	0.005
1	0.1	2	6.2M	10M	10M	5.1M	∞	0

Fig. 13—Slew rate test circuit for amplifier No. 1 of CA3060.

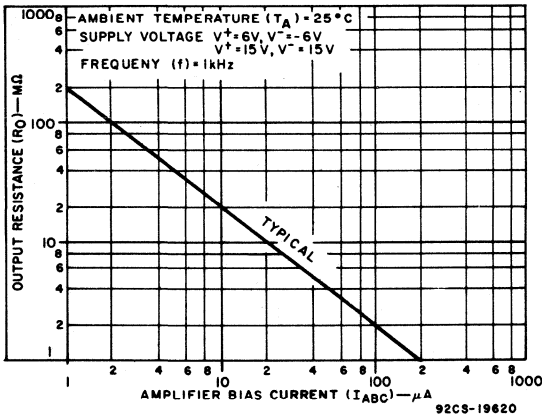


Fig. 14—Output resistance vs. amplifier bias current.

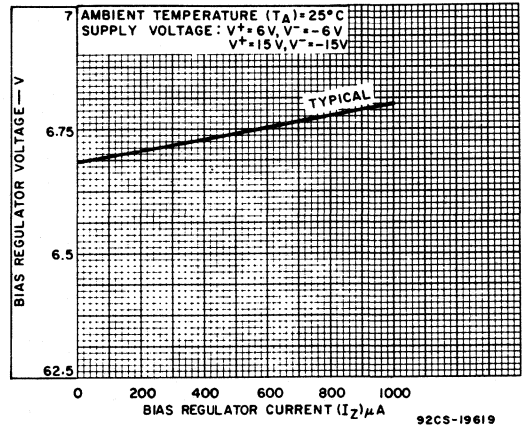


Fig. 15—Bias regulator voltage vs. bias regulator current.

OPERATING CONSIDERATIONS

The CA3060 consists of three operational amplifiers similar in form and application to conventional operational amplifiers but sufficiently different from the standard operational amplifier (op-amp) to justify some explanation of their characteristics. The amplifiers incorporated in the CA3060 are best described by the term Operational Transconductance Amplifier (OTA). The characteristics of an ideal OTA are similar to those of an ideal op-amp except that the OTA has an extremely high output impedance. Because of this inherent characteristic the output signal is best defined in terms of current which is proportional to the difference between the voltages of the two input terminals. Thus, the transfer characteristic is best described in terms of transconductance rather than voltage gain. Other than the difference given above, the characteristics tabulated on pages 3 and 4 of this data bulletin are similar to those of any typical op-amp.

The OTA circuitry incorporated in the CA3060 (See Fig. 16) provides the equipment designer with a wider variety of

circuit arrangements than does the standard op-amp; because as the curves in the data bulletin indicate, the user may select the optimum circuit conditions for a specific application simply by varying the bias conditions of each amplifier. If low power consumption, low bias, and low offset current, or high input impedance are primary design requirements, then low current operating conditions may be selected. On the other hand, if operation into a moderate load impedance is the primary consideration, then higher levels of bias may be used.

Bias Considerations for Op-Amp Applications

The operational transconductance amplifiers allow the circuit designer to select and control the operating conditions of the circuit merely by the adjustment of the input bias current I_{ABC} . This enables the designer to have complete control over transconductance, peak output current and total power consumption independent of supply voltage.

CA3060, CA3060A Types

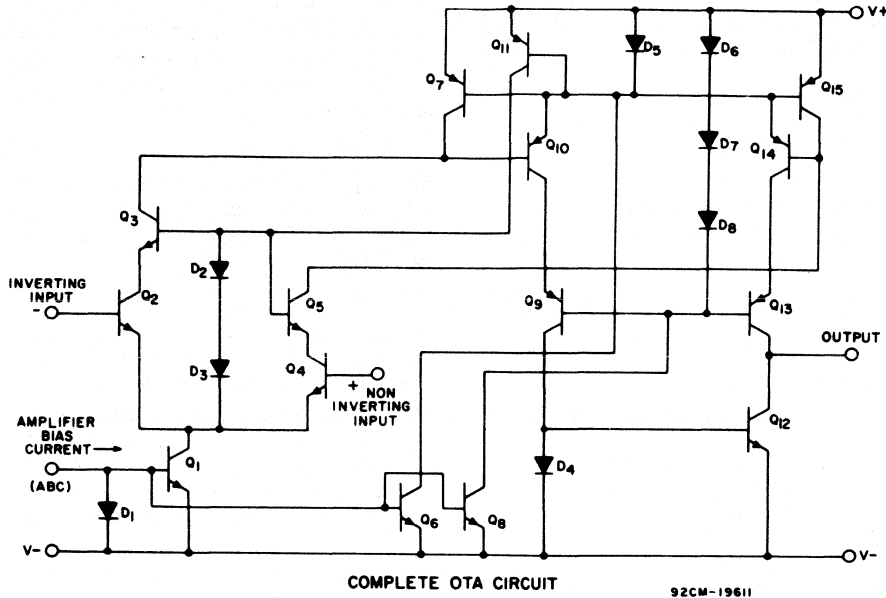


Fig. 16—Complete schematic diagram showing bias regulator and one of the three operational transconductance amplifiers.

In addition, the high output impedance makes these amplifiers ideal for applications where current summing is involved.

The design of a typical operational amplifier circuit (See Fig. 17) would proceed as follows:

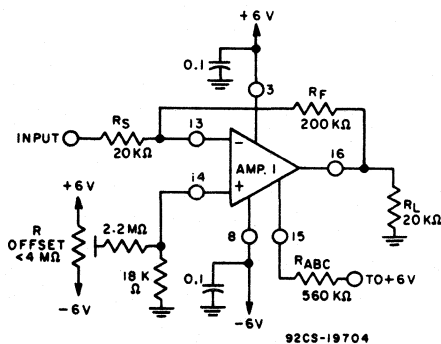


Fig. 17—20-dB amplifier using the CA3060.

Circuit Requirements

Closed loop voltage gain = 10 (20 dB)

Offset voltage adjustable to zero

Current drain as low as possible

Supply voltage = ± 6 V

Maximum input voltage = ± 50 mV

Input resistance = 20 k Ω

Load resistance = 20 k Ω

Device: CA3060

Calculation

1. Required transconductance g_{21} .

Assume that the open loop gain A_{OL} must be at least ten times the closed loop gain. Therefore, the forward transconductance required is given by

$$\begin{aligned} g_{21} &= A_{OL}/R_L \\ &= 100/18 \text{ k}\Omega \\ &\cong 5.5 \text{ mmho} \end{aligned}$$

($R_L = 20 \text{ k}\Omega$ in parallel with $200 \text{ k}\Omega$)

$$\cong 18 \text{ k}\Omega)$$

2. Selection of suitable amplifier bias current.

The amplifier bias current is selected from the minimum value curve of transconductance (Fig. 10a) to assure that the amplifier will provide sufficient gain. For the required g_{21} of 5.5 mmho an amplifier bias current I_{ABC} of 20 μA is suitable.

3. Determination of Output Swing Capability.

For a loop gain of 10 the output swing is ± 0.5 V and the peak load current 25 μA . However, the amplifier must also supply the necessary current through the feedback resistor and for $R_S = 20 \text{ k}\Omega$ than $R_F = 200 \text{ k}\Omega$ if $A_{OL} = 10$. Therefore, the feedback loading = $0.5/200 \text{ k}\Omega = 2.5 \mu\text{A}$.

The total amplifier current output requirements are, therefore, $\pm 27.5 \mu\text{A}$. Referring to the data given in Fig. 6a we see that for an amplifier bias current of 20 μA the amplifier output current is $\pm 40 \mu\text{A}$. This is obviously adequate and it is not necessary to change the amplifier bias current I_{ABC} .

4. Calculation of bias resistance.

For minimum supply current drain the amplifier bias current I_{ABC} should be fed directly from the supplies and not from the bias regulator. The value of the resistor R_{ABC} may be directly calculated using Ohm's law.

Linear Integrated Circuits

CA3060, CA3060A Types

$$R_{ABC} = \frac{V_{SUP} \cdot V_{ABC}}{I_{ABC}}$$

$$R_{ABC} = \frac{12 \cdot 0.63}{20 \times 10^{-6}}$$

$$= 568.5 \text{ k}\Omega \text{ or } \cong 560 \text{ k}\Omega$$

5. Calculation of offset adjustment circuit.

In order to reduce the loading effect of the offset adjustment circuit on the power supply, the offset control should be arranged to provide the necessary offset current. The source resistance of the non-inverting input is made equal to the source resistance of the inverting input.

$$\text{i.e. } \frac{20 \times 200 \times 10^6 \text{ ohms}}{220 \times 10^3} \cong 18 \text{ k}\Omega$$

Because the maximum offset voltage is 5 mV and an additional increment due to the offset current (Fig. 4) flowing through the source resistance

(i.e. $200 \times 10^{-9} \times 18 \times 10^3$ volts), therefore,

the Offset Voltage Range = 5 mV + 3.6 mV = ± 8.6 mV

The current necessary to provide this offset is

$$\frac{8.6 \times 10^{-3}}{18 \times 10^3} \text{ or } 0.48 \mu\text{A}$$

With a supply voltage of ± 6 V, this current can be provided by a 10 M Ω resistor. However, the stability of such a resistor is often questionable and a more realistic value of 2.2 M Ω was used in the final circuit.

OTHER CONSIDERATIONS

Capacitance Effects

The CA3060 is designed to operate at such low power levels that high impedance circuits must be employed. In designing such circuits, particularly feedback amplifiers, stray circuit capacitance must always be considered because of its adverse effect on frequency response and stability. For example a 10-k Ω load with a stray capacitance of 15 pF has a time constant of 1 MHz. Fig. 18 illustrates how a 10-k Ω 15-pF load modifies the frequency characteristic.

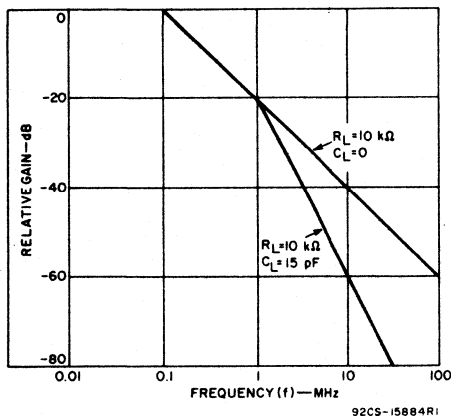


Fig. 18—Effect of capacitive loading on frequency response.

Capacitive loading also has an effect on slew rate; because the peak output current is established by the amplifier bias current, I_{ABC} (see Fig. 6a), the maximum slew rate is limited to the maximum rate at which the capacitance can be charged by the I_{OM} . Therefore,

$$SR = dV/dt = I_{OM}/C_L$$

where C_L is the total load capacitance including strays. This relationship is shown graphically in Fig. 19. When measuring slew rate for this data bulletin, care was taken to keep the total capacitive loading to 13 pF.

Phase Compensation

In many applications phase compensation will not be required for the amplifiers of the CA3060. When needed, compensation may easily be accomplished by a simple RC network at the input of the amplifier as shown in Fig. 13. The values given in Fig. 13 provide stable operation for the critical unity gain condition, assuming that capacitive loading on the output is 13 pF or less. Input phase compensation is recommended in order to maintain the highest possible slew rate.

In applications such as integrators, two OTAs may be cascaded to improve current gain. Compensation is best accomplished in this case with a shunt capacitor at the output of the first amplifier. The high gain following compensation assures a high slew rate.

APPLICATIONS

Having determined the operating points of the CA3060 amplifiers, they can now function in the same manner as conventional op-amps, and thus, are well suited for most op-amp applications, including inverting and non-inverting amplifiers, integrators, differentiators, summing amplifiers etc.

TRI-LEVEL COMPARATOR

Tri-level comparator circuits are an ideal application for the CA3060 since it contains the requisite three amplifiers. A tri-level comparator has three adjustable limits. If either the upper or lower limit is exceeded, the appropriate output is activated until the input signal returns to a selected intermediate limit. Tri-level comparators are particularly suited to many industrial control applications.

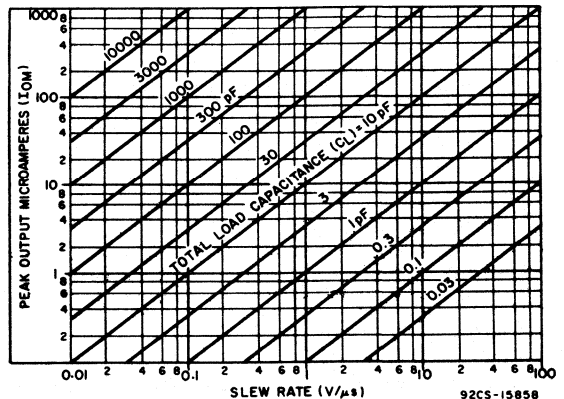


Fig. 19—Effect of load capacitance on slew rate.

CA3060, CA3060A Types

Circuit Description

Fig. 20 shows the block diagram of a tri-level comparator using the CA3060. Two of the three amplifiers are used to compare the input signal with the upper-limit and lower-

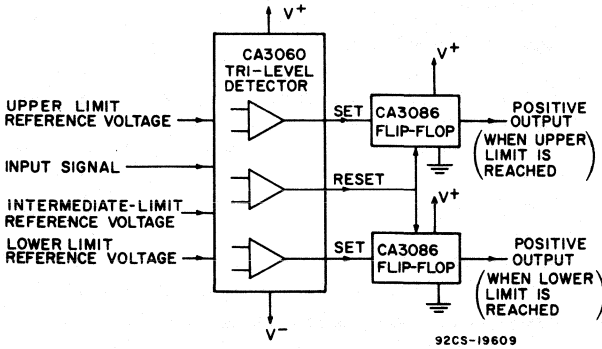


Fig.20—Functional block diagram of a tri-level comparator.

limit reference voltages. The third amplifier is used to compare the input signal with a selected value of intermediate-limit reference voltage. By appropriate selection or resistance ratios this intermediate-limit may be set to any voltage between the upper-limit and lower-limit values. The output of the upper-limit and lower-limit comparator sets the corresponding upper or lower-limit flip-flop. The activated flip-flop retains its state until the third comparator (intermediate-limit) in the CA3060 initiates a reset function, thereby indicating that the signal voltage has returned to the intermediate-limit selected. The flip-flops employ two CA3086 transistor-array IC's, with circuitry to provide separate "SET" and "POSITIVE OUTPUT" terminals.

The circuit diagram of a tri-level comparator appears in Fig. 21. Power is provided for the CA3060 via terminals 3 and 8 by ± 6 -volt supplies and the built-in regulator provides amplifier-bias-current (I_{ABC}) to the three amplifiers via terminal 1. Lower-limit and upper-limit reference voltages are selected by appropriate adjustment of potentiometers R1 and R2, respectively. When resistors R3 and R4 are equal in value (as shown), the intermediate-limit reference voltage is automatically established at a value midway between the lower-limit and upper-limit values. Appropriate variation of resistors R3 and R4 permits selection of other values of intermediate-limit voltages. Input signal (E_S) is applied to the three comparators via terminals 5, 12, and 14. The "SET" output lines trigger the appropriate flip-flop whenever the input signal reaches a limit value. When the input signal returns to an intermediate-value, the common flip-flop "RESET" line is energized. The loads in the circuits, shown in Fig. 21 are 5-V, 25-mA lamps.

Active Filters — Using the CA3060 as a Gyration

The high output impedance of the OTAs makes the CA3060 ideally suited for use as a gyrator in active filter applications. Fig. 22 shows two OTAs of the CA3060 connected as a gyrator in an active filter circuit. The OTAs in this circuit can make a $3\text{-}\mu\text{F}$ capacitor function as a floating 10-kilohm inductor across Terminals A and B. The measured Q of 13 (at a frequency of 1 Hz) of this inductor compares favorably with a calculated Q of 16. The 20-kilohm to 2-megohm attenuators in this circuit extend the dynamic range of the OTA by a factor of 100. The 100-kilohm potentiometer, across V^+ and V^- , tunes the inductor by varying the g_{21} of the OTAs, thereby changing the gyration resistance.

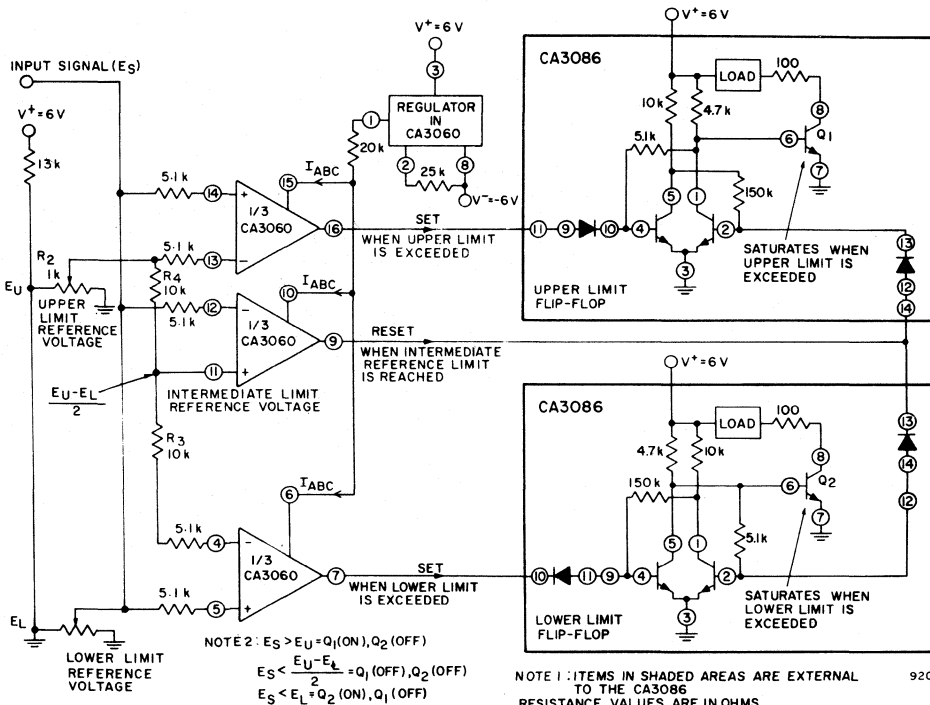
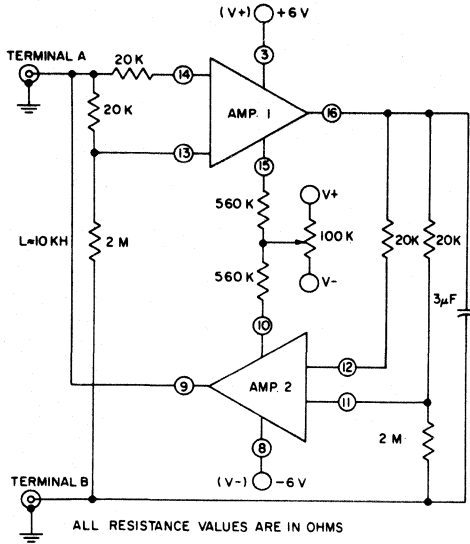


Fig.21—Tri-level comparator circuit.

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CA3060, CA3060A Types



92CS-1586IRI

Fig. 22—Two operational transconductance amplifiers of the CA3060 connected as a gyrator in an active filter circuit.

THREE CHANNEL MULTIPLEXER

Fig. 23 shows a schematic of a three channel multiplexer using a single CA3060 and a 3N138 MOS/FET as a buffer and power amplifier.

When the CA3060 is connected as a high-input impedance voltage follower, and strobe "ON," each amplifier is activated and the output swings to the level of the input of that amplifier. The cascade arrangement of each CA3060 amplifier with the MOS/FET provides an open loop voltage gain in excess of 100 dB, thus assuring excellent accuracy in the voltage follower mode with 100% feedback.

Operation at ± 6 volts is also possible with several minor changes. First, the resistance in series with amplifier bias current (I_{ABC}) terminal of each amplifier should be decreased to maintain 100 μ A of strobe—"ON" current at this lower supply voltage. Second, the drain resistance for the MOS/FET should be decreased to maintain the same value of source current. The low cost dual-gate protected MOS/FET, RCA-40841, may be used when operating at the low supply voltage.

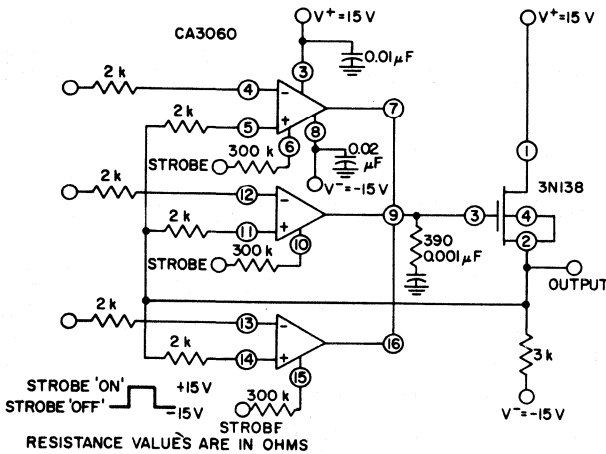
The phase compensation network consists of a single 390 Ω resistor and a 1000-pF capacitor, located at the interface of the CA3060 output and the MOS/FET gate. The bandwidth of the system is 1.5 MHz and the slew rate is 0.3 volts/ μ sec. The system slew rate is directly proportional to the value of the phase compensation capacitor. Thus, with higher gain settings where lower values of phase compensation capacitors are possible, the slew rate is proportionally increased.

NON LINEAR APPLICATIONS

AM Modulator (Two-Quadrant Multiplier)

Fig. 24 shows Amplifier No. 3 of the CA3060 used in an AM modulator or 2-quadrant multiplier circuit. When modulation is applied to the amplifier bias input, Terminal B, and the carrier frequency to the differential input, Terminal A, the waveform, shown in Fig. 24, is obtained. Fig. 24 is a result of adjusting the input offset control to balance the circuit so that no modulation can occur at the output without a carrier input. The linearity of the modulator is indicated by the solid trace of the superimposed modulating frequency. The maximum depth of modulation is determined by the ratio of the peak input modulating voltage to V_T .

The two-quadrant multiplier characteristic of this modulator is easily seen if modulation and carrier are reversed as shown in Fig. 24. The polarity of the output must follow that of the differential input; therefore, the output is positive only during the positive half cycle of the modulation and negative only in the second half cycle. Note, that both the input and output signals are referenced to ground. The output signal is zero when either the differential input or I_{ABC} are zero.



92CS-19610

Fig. 23—Three-channel multiplexer.

CA3060, CA3060A Types

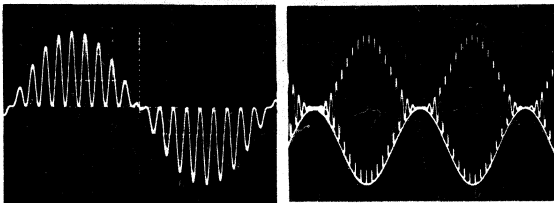
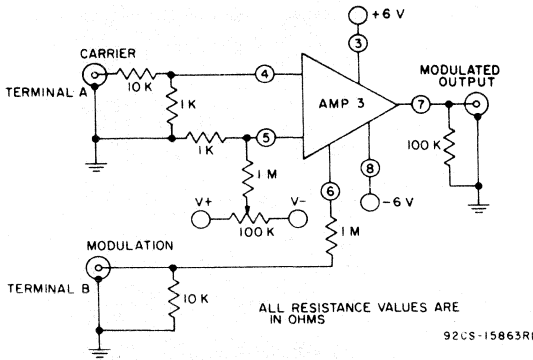


Fig.24—Two-quadrant multiplier circuit using the CA3060 with associated waveforms.

Four-Quadrant Multiplier

The CA3060 is also useful as a four-quadrant multiplier. A block diagram of such a multiplier, utilizing Amplifier Nos. 1, 2, and 3, is shown in Fig. 25 and a typical circuit is shown in Fig. 26. The multiplier consists of a single CA3060 and, as in the two-quadrant multiplier, exhibits no level shift between input and output. In Fig. 25, Amplifier No. 1 is connected as an inverting amplifier for the X-input signal. The output current of Amplifier No. 1 is calculated as follows:

$$I_{O(1)} = [-V_X] [g_{21(1)}] \tag{Eq.3}$$

Ampl. No. 2 is a non-inverting amplifier so that

$$I_{O(2)} = [+V_X] [g_{21(2)}] \tag{Eq. 4}$$

Because the amplifier output impedances are high, the load current is the sum of the two output currents, for an output voltage

$$V_O = V_X R_L [g_{21(2)} - g_{21(1)}] \tag{Eq. 5}$$

The transconductance is approximately proportional to the amplifier bias current; therefore, by varying the bias current the g_{21} is also controlled. Amplifier No. 2 bias current is proportional to the Y-input signal and is expressed as

$$I_{ABC(2)} \approx \frac{(V-) + V_Y}{R_1} \tag{Eq. 6}$$

Hence,

$$g_{21(2)} \approx k [(V-) + V_Y]. \tag{Eq. 7}$$

Bias for Amplifier No. 1 is derived from the output of Amplifier No. 3 which is connected as a unity-gain inverting amplifier. $I_{ABC(1)}$, therefore, varies inversely with V_Y . And by the same reasoning as above

$$g_{21(1)} \approx k [(V-) - V_Y]. \tag{Eq. 8}$$

Combining equation 5, 7, and 8 yields:

$$V_O \approx V_X \cdot k \cdot R_L \left\{ [(V-) + V_Y] - [(V-) - V_Y] \right\} \text{ or } V_O \approx 2k R_L V_X V_Y$$

Fig. 26 shows the actual circuit including all the adjustments associated with differential input and an adjustment for equalizing the gains of Amplifiers No. 1 and No. 2. Adjustment of the circuit is quite simple. With both the X and Y voltages at zero, connect Terminal 10 to Terminal 8. This procedure disables Amplifier No. 2 and permits adjusting the offset voltage of Amplifier No. 1 to zero by means of the 100-k Ω potentiometer. Next, remove the short between Terminals 10 and 8 and connect Terminal 15 to Terminal 8. This step disables Amplifier No. 1 and permits Amplifier No. 2 to be zeroed with the other potentiometer. With AC signals on both the X and Y input, R3 and R11 are adjusted for symmetrical output signals. Fig. 27 shows the output waveform with the multiplier adjusted. The voltage waveform in Fig. 27a shows suppressed carrier modulation of 1-kHz carrier with a triangular wave.

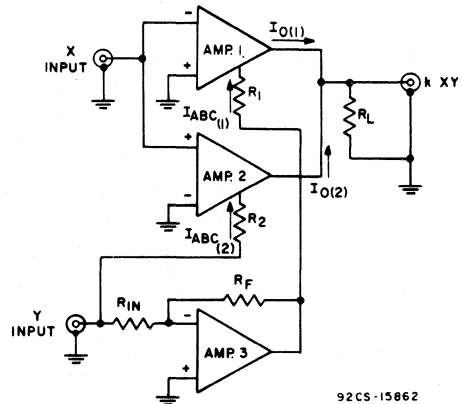


Fig.25—Four-quadrant multiplier using the CA3060.

Figures 27b and 27c, respectively, show the squaring of a triangular wave and a sine wave. Notice that in both cases the outputs are always positive and return to zero after each cycle.

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CA3060, CA3060A Types

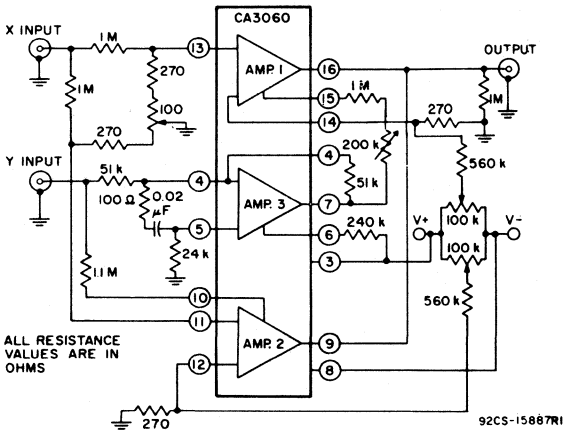


Fig.26—Typical four-quadrant multiplier circuit.

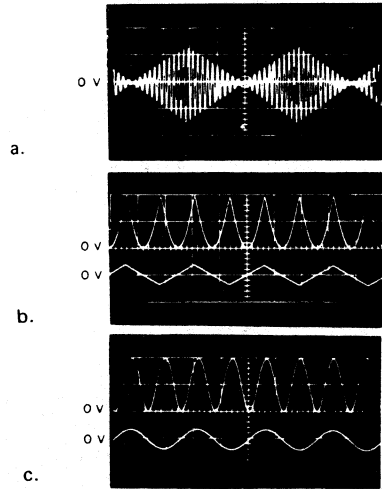
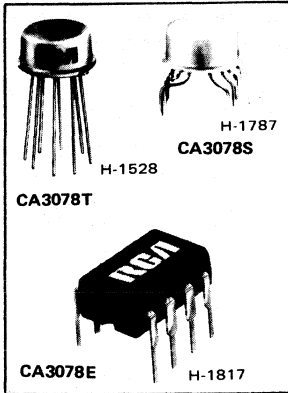


Fig.27—Voltage waveforms of four-quadrant multiplier circuit.



Micropower Operational Amplifier

Features:

- Low standby power: as low as 700 nW
- Wide supply voltage range: ± 0.75 to ± 15 V
- High peak output current: 6.5 mA min.
- Adjustable quiescent current
- Output short-circuit protection

Applications:

- | | |
|------------------------|--------------------|
| ■ Portable electronics | ■ Instrumentation |
| ■ Medical electronics | ■ Telemetry |
| | ■ Intrusion alarms |

The RCA-CA3078 and CA3078A are high-gain monolithic operational amplifiers which can deliver milliamperes of current yet only consume microwatts of standby power. Their operating points are externally adjustable and frequency compensation may be accomplished with one external capacitor. The CA3078 and CA3078A provide the designer with the opportunity to tailor the frequency response and improve the slew rate without sacrificing power. Operation with a single 1.5-volt battery is a practical reality with these devices.

The CA3078A is a premium device having a supply voltage range of $V^{\pm} = 0.75$ to $V^{\pm} = 15$ V and an operating temperature range of -25°C to $+125^{\circ}\text{C}$. The CA3078 has the same lower supply voltage limit but the upper limit is $V^{+} = +6$ V and $V^{-} = -6$ V. The operating temperature range is from 0°C to $+70^{\circ}\text{C}$.

The CA3078 and CA3078A are supplied in the standard 8-lead TO-5 package ("T" suffix), the 8-lead dual-in-line formed-lead "DIL-CAN" package ("S" suffix), or the 8-lead dual-in-line plastic "MINI-DIP" package ("E" suffix).

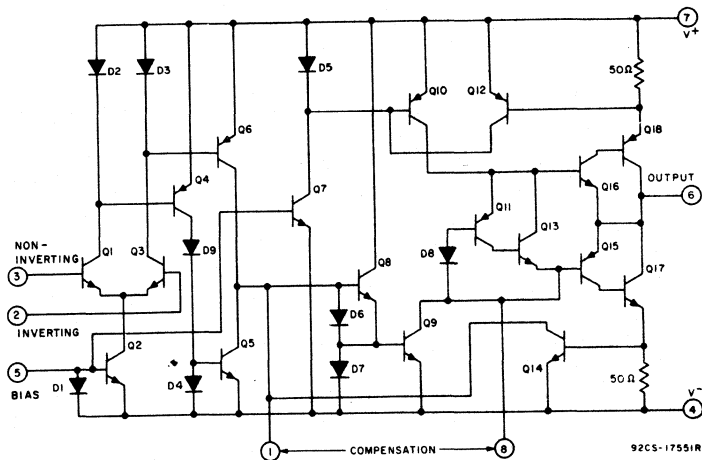


Fig. 1 - Schematic diagram of the CA3078 and CA3078A.

Linear Integrated Circuits

CA3078, CA3078A Types

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

	CA3078A	CA3078
DC Supply Voltage (between V^+ and V^- terminal)	36 V	14 V
Differential Input Voltage	± 6 V	± 6 V
DC Input Voltage	V^+ to V^-	V^+ to V^-
Input Signal Current	0.1 mA	0.1 mA
Output Short-Circuit Duration*	No Limitation	No Limitation
Device Dissipation	150 mW (up to 125°C)	500 mW (up to 70°C)
Temperature Range:		
Operating	-55 to $+125^\circ\text{C}$	0 to $+70^\circ\text{C}$
Storage	-65 to $+150^\circ\text{C}$	-65 to $+150^\circ\text{C}$
Lead Temperature (During Soldering):		
At distance $1/16 \pm 1/32$ in. (1.59 ± 0.79 mm) from case for 10s max.	$+300^\circ\text{C}$	$+300^\circ\text{C}$

* Short circuit may be applied to ground or to either supply.

ELECTRICAL CHARACTERISTICS For Equipment Design

CHARACTERISTICS SYMBOLS	TEST CONDITIONS	CA3078A LIMITS						CA3078 LIMITS						UNITS		
		$R_{SET} = 5.1 \text{ M}\Omega, I_Q = 20 \mu\text{A}$														
		$T_A = 25^\circ\text{C}$						$T_A = -55$ to 125°C			$T_A = 25^\circ\text{C}$				$T_A = 0$ to 70°C	
		V^+ & V^-	R_S k Ω	R_L k Ω	MIN.	TYP.	MAX.	MIN.	MAX.	MIN.	TYP.	MAX.	MIN.		MAX.	
V_{IO}	6	≤ 10	—	—	0.70	3.5	—	4.5	—	1.3	4.5	—	5	mV		
I_{IO}		—	—	—	0.50	2.5	—	5.0	—	6	32	—	40	nA		
I_{IB}		—	—	—	7	12	—	50	—	60	170	—	200	nA		
A_{OL}		≥ 10	92	100	—	90	—	88	92	—	86	—	—	dB		
I_Q		—	—	—	20	25	—	45	—	100	130	—	150	μA		
P_D		—	—	—	240	300	—	540	—	1200	1560	—	1800	μW		
V_{OM}		≥ 10	± 5.1	± 5.3	—	± 5	—	± 5.1	± 5.3	—	± 5	—	—	V		
V_{ICR}		≤ 10	—	—	-5.5 to $+5.8$	—	-5 to $+5$	—	—	-5.5 to $+5.8$	—	-5 to $+5$	—	V		
CMRR		≤ 10	—	80	115	—	—	—	80	110	—	—	—	dB		
I_{OM}^+ or I_{OM}^-		—	—	—	12	—	6.5	30	—	12	—	6.5	30	mA		
$\Delta V_{IO}/\Delta V^+$		≤ 10	—	76	105	—	—	—	76	93	—	—	—	$\mu\text{V/V}$		
$\Delta V_{IO}/\Delta V^-$		—	—	76	105	—	—	—	76	93	—	—	—			
					$R_{SET} = 13 \text{ M}\Omega, I_Q = 20 \mu\text{A}$											
V_{IO}	15	≤ 10	—	—	1.4	3.5	—	4.5	—	—	—	—	—	mV		
A_{OL}		≥ 10	92	100	—	88	—	—	—	—	—	—	—	dB		
I_Q		—	—	—	20	30	—	50	—	—	—	—	—	μA		
P_D		—	—	—	600	750	—	1350	—	—	—	—	—	μW		
V_{OM}		≥ 10	± 13.7	± 14.1	—	± 13.5	—	—	—	—	—	—	—	V		
CMRR		≤ 10	—	80	106	—	—	—	—	—	—	—	—	dB		
I_{IB}		—	—	—	7	14	—	55	—	—	—	—	—	nA		
I_{IO}		—	—	—	0.50	2.7	—	5.5	—	—	—	—	—	nA		

Operational Amplifiers CA3078, CA3078A Types

ELECTRICAL CHARACTERISTICS, at $T_A = 25^\circ\text{C}$

Typical Values Intended Only for Design Guidance

CHARACTERISTICS SYMBOLS	TYPICAL VALUES				UNITS
	CA3078A		CA3078		
	$V^+ = +1.3\text{ V}$, $V^- = -1.3\text{ V}$ $R_{SET} = 2\text{ M}\Omega$ $I_Q = 10\text{ }\mu\text{A}$	$V^+ = +0.75\text{ V}$, $V^- = -0.75\text{ V}$ $R_{SET} = 10\text{ M}\Omega$ $I_Q = 1\text{ }\mu\text{A}$	$V^+ = +1.3\text{ V}$, $V^- = -1.3\text{ V}$ $R_{SET} = 2\text{ M}\Omega$ $I_Q = 10\text{ }\mu\text{A}$	$V^+ = +0.75\text{ V}$, $V^- = -0.75\text{ V}$ $R_{SET} = 10\text{ M}\Omega$ $I_Q = 1\text{ }\mu\text{A}$	
V_{IO}	0.7	0.9	1.3	1.5	mV
I_{IO}	0.3	0.054	1.7	0.5	nA
I_{IB}	3.7	0.45	9	1.3	nA
A_{OL}	84	65	80	60	dB
I_Q	10	1	10	1	μA
P_D	26	1.5	26	1.5	μW
V_{OPP}	1.4	0.3	1.4	0.3	V
V_{ICR}	-0.8 to +1.1	-0.2 to +0.5	-0.8 to +1.1	-0.2 to +0.5	V
CMRR	100	90	100	90	dB
I_{OM}^\pm	12	0.5	12	0.5	mA
$\Delta V_{IO}/\Delta V^\pm$	20	50	20	50	$\mu\text{V}/\text{V}$

Typical Values Intended Only for Design Guidance at $T_A = 25^\circ\text{C}$ and $V^+ = +6\text{ V}$, $V^- = -6\text{ V}$

CHARACTERISTICS SYMBOLS	TEST CONDITIONS	CA3078A		CA3078	UNITS
		$R_{SET} = 5.1\text{ M}\Omega$ $I_Q = 20\text{ }\mu\text{A}$	$R_{SET} = 1\text{ M}\Omega$ $I_Q = 100\text{ }\mu\text{A}$	$R_{SET} = 1\text{ M}\Omega$ $I_Q = 100\text{ }\mu\text{A}$	
$\Delta V_{IO}/\Delta T_A$	$R_S \leq 10\text{ k}\Omega$	5	6	6	$\mu\text{V}/^\circ\text{C}$
$\Delta V_{IO}/\Delta T_A$	$R_S \leq 10\text{ k}\Omega$	6.3	70	70	$\text{pA}/^\circ\text{C}$
BW_{OL}	3dB pt.	0.3	2	2	kHz
SR	See Figs. 20, 21	0.027	0.04	0.04	V/ μs
		0.5	1.5	1.5	
—	10% to 90% Rise Time	3	2.5	2.5	μs
R_I		7.4	1.7	0.87	$\text{M}\Omega$
R_O		1	0.8	0.8	$\text{k}\Omega$
e_N (10 Hz)	$R_S = 0$	40	—	25	$\text{nV}/\sqrt{\text{Hz}}$
i_N (10 Hz)	$R_S = 1\text{ M}\Omega$	0.25	—	1	$\text{pA}/\sqrt{\text{Hz}}$

Linear Integrated Circuits

CA3078, CA3078A Types

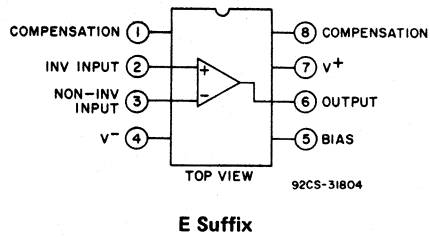
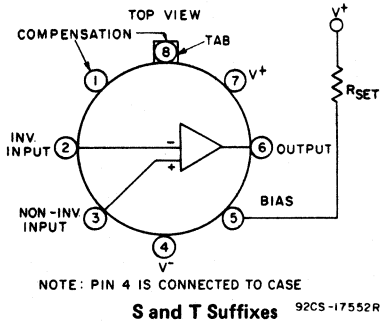


Fig. 2 - Functional diagrams.

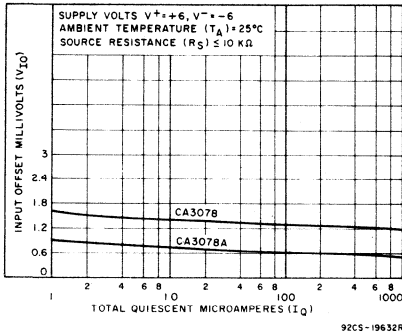


Fig. 3 - Input offset voltage vs. total quiescent current.

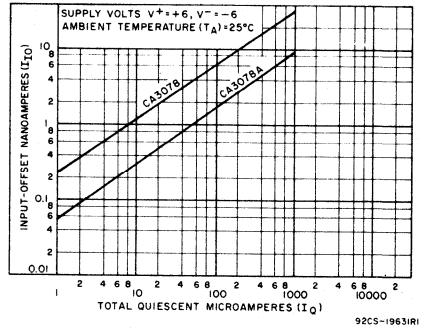


Fig. 4 - Input offset current vs. total quiescent current.

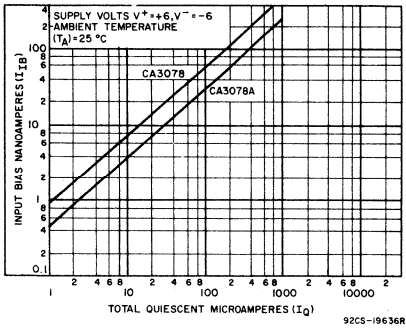


Fig. 5 - Input bias current vs. total quiescent current.

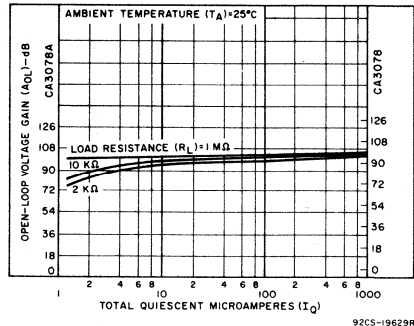


Fig. 6 - Open-loop voltage gain vs. total quiescent current.

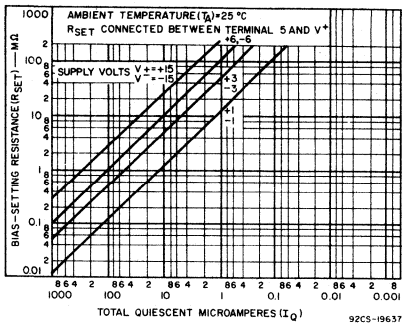


Fig. 7 - Bias-setting resistance vs. total quiescent current.

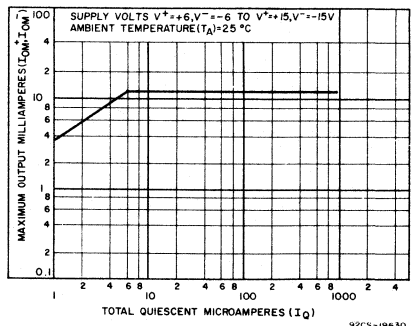


Fig. 8 - Maximum output current vs. total quiescent current.

Operational Amplifiers

CA3078, CA3078A Types

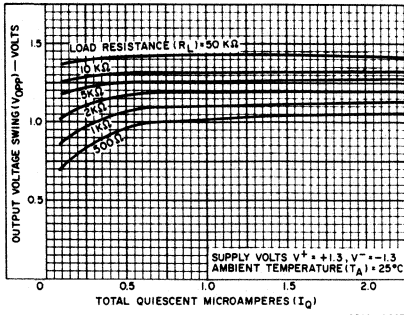


Fig. 9 – Output voltage swing vs. total quiescent current.

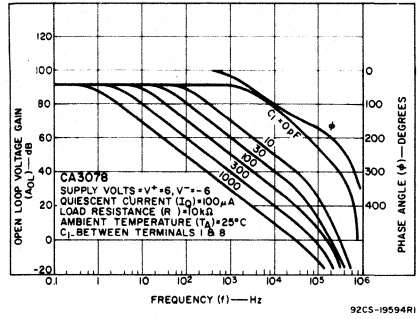


Fig. 10 – Open-loop voltage gain vs. frequency for $I_Q = 100 \mu\text{A}$ – CA3078.

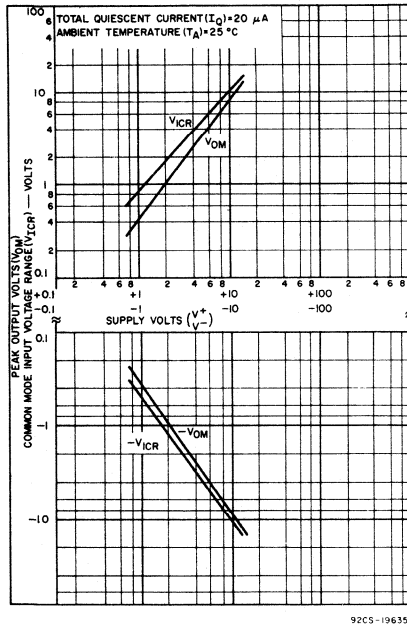


Fig. 11 – Output and common-mode voltage vs. supply voltage.

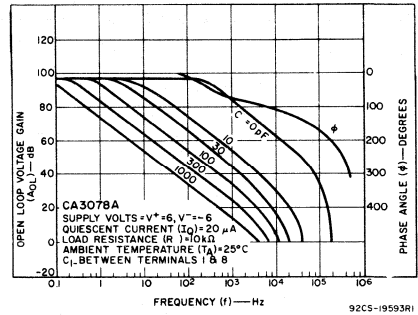


Fig. 12 – Open-loop voltage gain vs. frequency for $I_Q = 20 \mu\text{A}$ – CA3078A.

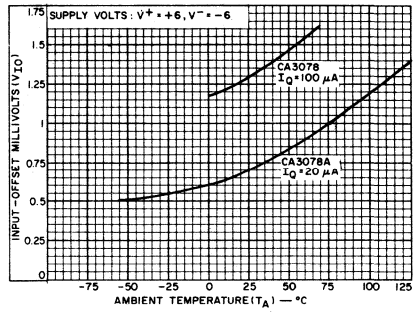


Fig. 13 – Input offset voltage vs. temperature.

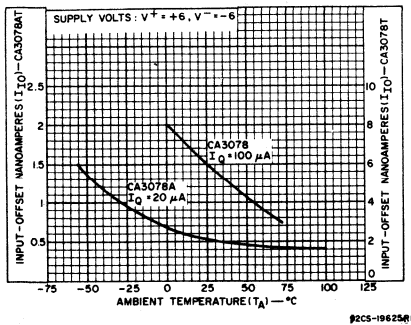


Fig. 14 – Input offset current vs. temperature.

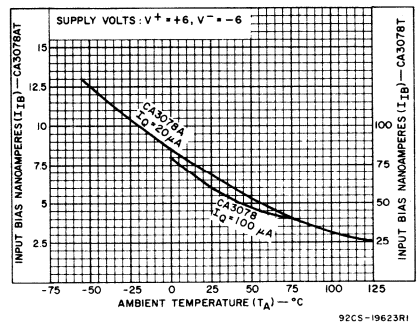


Fig. 15 – Input bias current vs. temperature.

Linear Integrated Circuits

CA3078, CA3078A Types

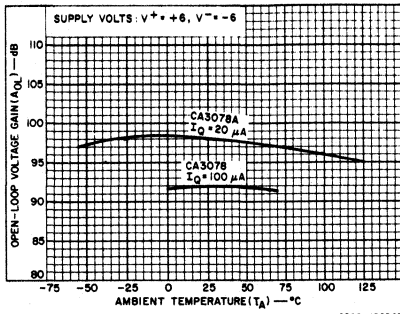


Fig. 16 — Open-loop voltage gain vs. temperature.

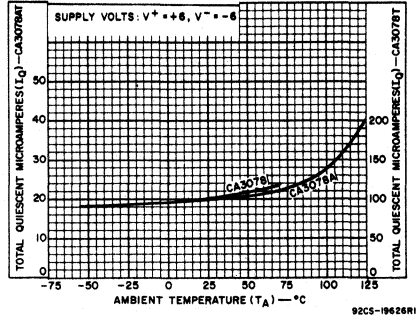


Fig. 17 — Total quiescent current vs. temperature.

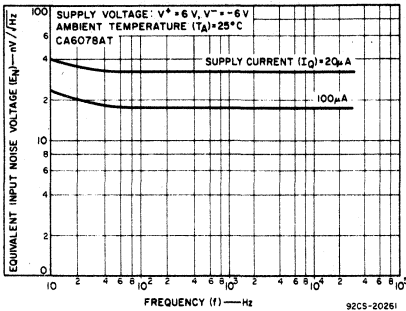


Fig. 18 — Equivalent input noise voltage vs. frequency.

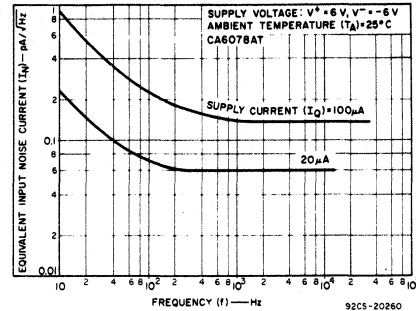


Fig. 19 — Equivalent input noise current vs. frequency.

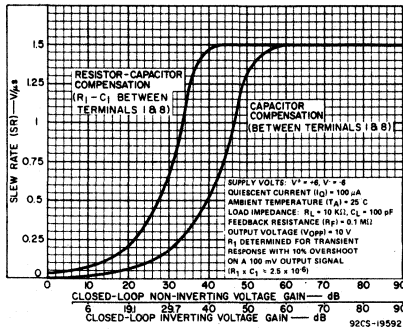


Fig. 20 — Slew rate vs. closed-loop gain for $I_Q = 100 \mu A$ — CA3078.

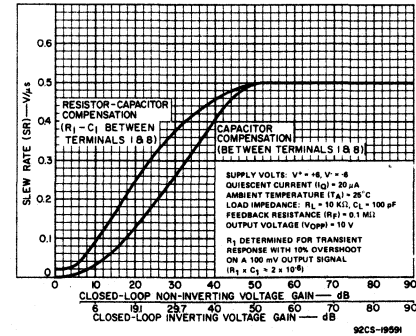


Fig. 21 — Slew rate vs. closed-loop gain for $I_Q = 20 \mu A$ — CA3078A.

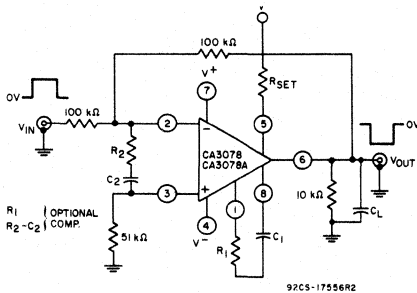


Fig. 22 — Transient response and slew-rate, unity gain (inverting) test circuit.

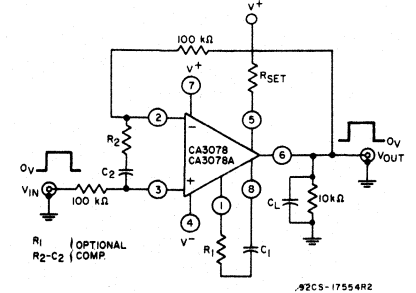


Fig. 23 — Slew-rate, unity gain (non-inverting) test circuit.

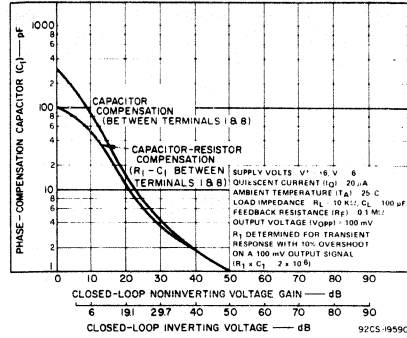
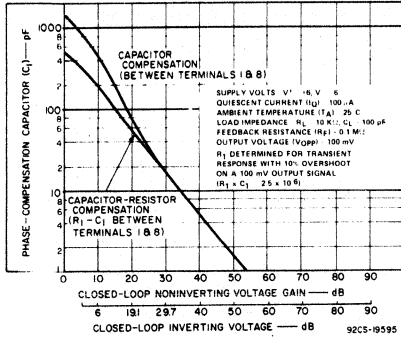


Table I - Unity-gain slew rate vs. compensation - CA3078 and CA3078A

SUPPLY VOLTS: $V^+ = 6, V^- = -6$		TRANSIENT RESPONSE: 10% OVERSHOOT FOR AN OUTPUT VOLTAGE OF 100 mV								
OUTPUT VOLTAGE (V_O) = ± 5 V		AMBIENT TEMPERATURE (T_A) = 25°C								
LOAD RESISTANCE (R_L) = 10 k Ω										
COMPENSATION TECHNIQUE	UNITY GAIN (INVERTING) Fig. 22					UNITY GAIN (NON-INVERTING) Fig. 23				
	R1	C1	R2	C2	SLEW RATE	R1	C1	R2	C2	SLEW RATE
CA3078 - $I_Q = 100 \mu A$	k Ω	pF	k Ω	μF	V/ μs	k Ω	pF	k Ω	μF	V/ μs
Single Capacitor	0	750	∞	0	0.0085	0	1500	∞	0	0.0095
Resistor & Capacitor	3.5	350	∞	0	0.04	5.3	500	∞	0	0.024
Input	∞	0	0.25	0.306	0.67	∞	0	0.311	0.45	0.67
CA3078A - $I_Q = 20 \mu A$										
Single Capacitor	0	300	∞	0	0.0095	0	800	∞	0	0.003
Resistor & Capacitor	14	100	∞	0	0.027	34	125	∞	0	0.02
Input	∞	0	0.644	0.156	0.29	∞	0	0.77	0.4	0.4

OPERATING CONSIDERATIONS

Compensation Techniques

The CA3078A and CA3078 can be phase-compensated with one or two external components depending upon the closed-loop gain, power consumption, and speed desired. The recommended compensation is a resistor in series with a capacitor connected from terminal 1 to terminal 8. Values of the resistor and capacitor required for compensation as a function of closed loop gain are shown in Figs. 24 and 25. These curves represent the compensation necessary at quiescent currents of 100 μA and 20 μA , respectively, for a transient response with 10% overshoot. Figs. 20 and 21 show the slew rates that can be obtained with the two different compensation tech-

niques. Higher speeds can be achieved with input compensation, but this increases noise output. Compensation can also be accomplished with a single capacitor connected from terminal 1 to terminal 8, with speed being sacrificed for simplicity. Table I gives an indication of slew rates that can be obtained with various compensation techniques at quiescent currents of 100 μA and 20 μA .

Single Supply Operation

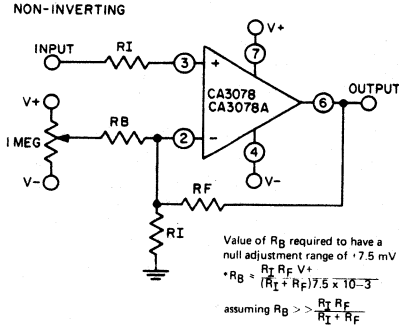
The CA3078A and CA3078 can operate from a single supply with a minimum total supply voltage of 1.5 volts. Figs. 27 and 28 show the CA3078A or CA3078 in inverting the non-inverting 20-dB amplifier configurations utilizing a 1.5-volt type "AA" cell for a supply. The total power consumption for

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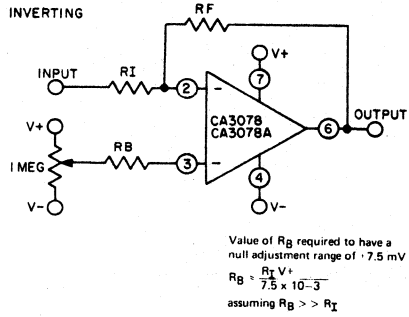
CA3078, CA3078A Types

either circuit is approximately 675 nano-watts. The output voltage swing in this

configuration is 300 mV p-p with a 20 kΩ load.



92CS-20812R2



92CS-20813R2

Fig. 26 – Offset voltage null circuits.

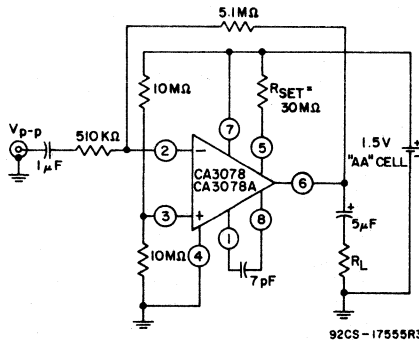


Fig. 27 – Inverting 20-dB amplifier circuit.

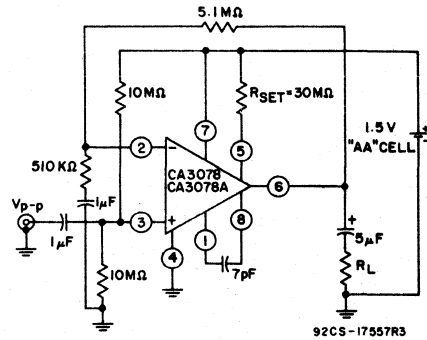


Fig. 28 – Non inverting 20-dB amplifier circuit.

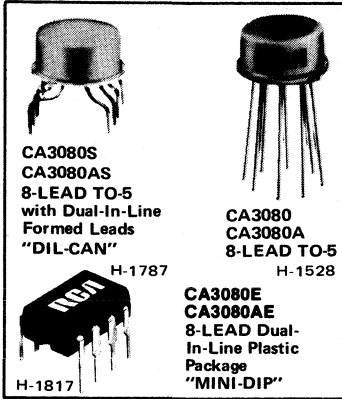
CA3080, CA3080A Types

Operational Transconductance Amplifiers (OTA's)

Gatable-Gain Blocks

Features:

- Slew rate (unity gain, compensated): $50 \text{ V}/\mu\text{s}$
- Adjustable power consumption: $10 \mu\text{W}$ to 30 mW
- Flexible supply voltage range: $\pm 2 \text{ V}$ to $\pm 15 \text{ V}$
- Fully adjustable gain: 0 to $g_m R_L$ limit
- Tight g_m spread: CA3080 (2:1), CA3080A (1.6:1)
- Extended g_m linearity: 3 decades



The RCA-CA3080 and CA3080A types are Gatable-Gain Blocks which utilize the unique operational-transconductance-amplifier (OTA) concept described in Application Note ICAN-6668, "Applications of the CA3080 and CA3080A High-Performance Operational Transconductance Amplifiers".

The CA3080 and CA3080A types have differential input and a single-ended, push-pull, class A output. In addition, these types have an amplifier bias input which may be used either for gating or for linear gain control. These types also have a high output impedance and their transconductance (g_m) is directly proportional to the amplifier bias current (I_{ABC}).

The CA3080 and CA3080A types are notable for their excellent slew rate ($50 \text{ V}/\mu\text{s}$), which makes them especially useful for multiplex and fast unity-gain voltage followers. These types are especially applicable for multiplex applications because power is consumed only when the devices are in the "ON" channel state.

The CA3080A is rated for operation over the full military-temperature range (-55 to $+125^\circ\text{C}$) and its characteristics are specifically controlled for applications such as sample-and-hold, gain-control, multiplex, etc. Operational transconductance amplifiers are also useful in programmable power-switch applications, e.g., as described in Application Note ICAN-6048, "Some Applications of a Programmable Power Switch/Amplifier" (CA3094, CA3094A, CA3094B).

These types are supplied in the 8-lead TO-5-style package (CA3080, CA3080A), and in the 8-lead TO-5-style package with dual-in-line formed leads ("DIL-CAN", CA3080S, CA3080AS), and in the 8-lead dual-in-line plastic ("MINI-DIP") package (CA3080E, CA3080AE), and in chip form (CA3080H).

Applications:

- Sample and hold
- Multiplex
- Voltage follower
- Multiplier
- Comparator

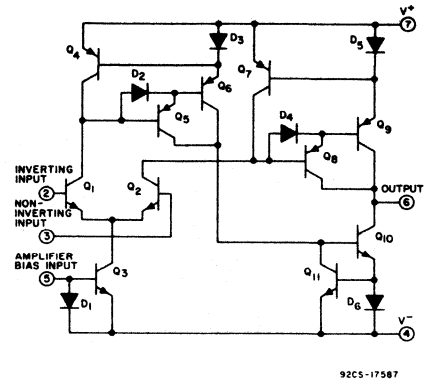


Fig. 1 — Schematic diagram for CA3080 and CA3080A.

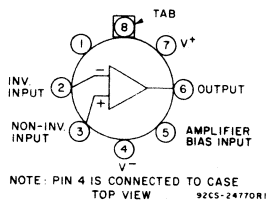
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CA3080, CA3080A Types

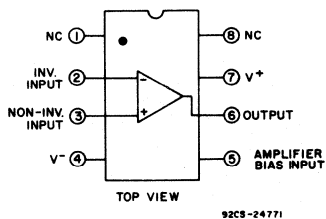
MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE (Between V^+ and V^- terminals)	36 V
DIFFERENTIAL INPUT VOLTAGE	±5 V
DC INPUT VOLTAGE	V^+ to V^-
INPUT SIGNAL CURRENT	1 mA
AMPLIFIER BIAS CURRENT	2 mA
OUTPUT SHORT-CIRCUIT DURATION*	Indefinite
DEVICE DISSIPATION	125 mW
TEMPERATURE RANGE:	
Operating	
CA3080, CA3080E, CA3080S	0 to +70 °C
CA3080A, CA3080AE, CA3080AS	-55 to +125 °C
Storage	
	-65 to +150 °C
LEAD TEMPERATURE (During Soldering):	
At distance 1/16 ± 1/32 in. (1.59 ± 0.79 mm)	
from case for 10 s max.	+265 °C

* Short circuit may be applied to ground or to either supply.



TO-5 Style Package



Plastic Package (E Suffix)

Fig.2 — Functional diagrams.

TYPICAL CHARACTERISTICS CURVES AND TEST CIRCUITS FOR THE CA3080 AND CA3080A

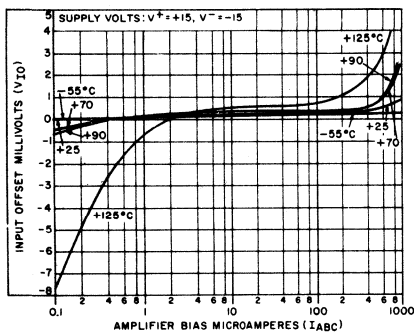


Fig.3 — Input offset voltage as a function of amplifier bias current.

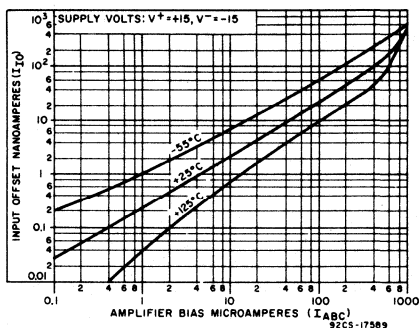


Fig.4 — Input offset current as a function of amplifier bias current.

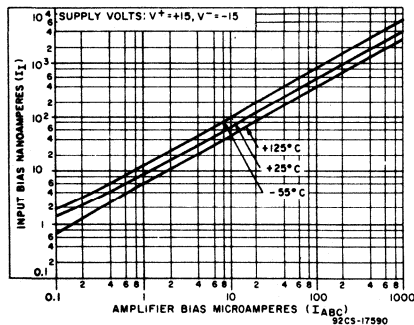


Fig.5 — Input bias current as a function of amplifier bias current.

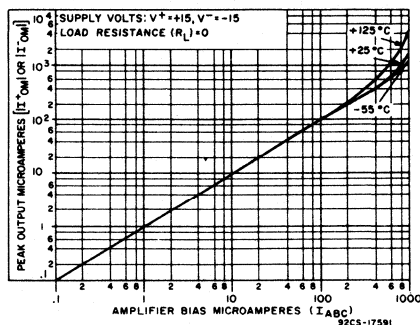


Fig.6 — Peak output current as a function of amplifier bias current.

ELECTRICAL CHARACTERISTICS
For Equipment Design

CHARACTERISTIC	TEST CONDITIONS $V^+ = 15\text{ V}$, $V^- = -15\text{ V}$ $I_{ABC} = 500\ \mu\text{A}$ $T_A = 25^\circ\text{C}$ (unless indicated otherwise)	CA3080 CA3080E CA3080S LIMITS			UNITS	
		Min.	Typ.	Max.		
Input Offset Voltage	V_{IO}	—	0.4	5	mV	
	$T_A = 0\text{ to }70^\circ\text{C}$	—	—	6		
Input Offset Current	I_{IO}	—	0.12	0.6	μA	
Input Bias Current	I_I	—	2	5	μA	
	$T_A = 0\text{ to }70^\circ\text{C}$	—	—	7		
Forward Transconductance (large signal)	g_m	6700	9600	13000	μmho	
	$T_A = 0\text{ to }70^\circ\text{C}$	5400	—	—		
Peak Output Current	$ I_{OM} $	$R_L = 0$	350	500	μA	
		$R_L = 0, T_A = 0\text{ to }70^\circ\text{C}$	300	—		
Peak Output Voltage: Positive	V^{+OM}	$R_L = \infty$	12	13.5	V	
Negative	V^{-OM}		—12	—14.4		
Amplifier Supply Current	I_A		0.8	1	1.2	mA
Device Dissipation	P_D		24	30	36	mW
Input Offset Voltage Sensitivity: Positive	$\Delta V_{IO}/\Delta V^+$		—	—	150	$\mu\text{V/V}$
Negative	$\Delta V_{IO}/\Delta V^-$		—	—	150	
Common-Mode Rejection Ratio	CMRR		80	110	—	dB
Common-Mode Input-Voltage Range	V_{ICR}		12 to —12	13.6 to —14.6	—	V
Input Resistance	R_I		10	26	—	k Ω

ELECTRICAL CHARACTERISTICS
Typical Values Intended Only for Design GuidanceCA3080
CA3080E
CA3080S

Input Offset Voltage	V_{IO}	$I_{ABC} = 5\ \mu\text{A}$	0.3	mV
Input Offset Voltage Change	$ \Delta V_{IO} $	$I_{ABC} = 500\ \mu\text{A}$ to $I_{ABC} = 5\ \mu\text{A}$	0.2	mV
Peak Output Current	I_{OM}	$I_{ABC} = 5\ \mu\text{A}$	5	μA
Peak Output Voltage: Positive	V^{+OM}	$I_{ABC} = 5\ \mu\text{A}$	13.8	V
Negative	V^{-OM}		—14.5	
Magnitude of Leakage Current		$I_{ABC} = 0, V_{TP} = 0$	0.08	nA
		$I_{ABC} = 0, V_{TP} = 36\text{ V}$	0.3	
Differential Input Current		$I_{ABC} = 0, V_{DIFF} = 4\text{ V}$	0.008	nA
Amplifier Bias Voltage	V_{ABC}		0.71	V
Slew Rate: Maximum (uncompensated)	SR		75	V/ μs
Unity Gain (compensated)			50	
Open-Loop Bandwidth	BWOL		2	MHz
Input Capacitance	C_I	$f = 1\text{ MHz}$	3.6	pF
Output Capacitance	C_O	$f = 1\text{ MHz}$	5.6	pF
Output Resistance	R_O		15	M Ω
Input-to-Output Capacitance	C_{I-O}	$f = 1\text{ MHz}$	0.024	pF
Propagation Delay	t_{PHL}, t_{PLH}	$I_{ABC} = 500\ \mu\text{A}$	45	ns

Linear Integrated Circuits

CA3080, CA3080A Types

ELECTRICAL CHARACTERISTICS For Equipment Design

CHARACTERISTIC	TEST CONDITIONS $V^+ = 15\text{ V}$, $V^- = -15\text{ V}$ $I_{ABC} = 500\text{ }\mu\text{A}$ $T_A = 25^\circ\text{C}$ (unless indicated otherwise)	CA3080A CA3080AE CA3080AS LIMITS			UNITS	
		Min.	Typ.	Max.		
Input Offset Voltage V_{IO}	$I_{ABC} = 5\text{ }\mu\text{A}$	—	0.3	2	mV	
		—	0.4	2		
	$T_A = -55\text{ to }+125^\circ\text{C}$	—	—	5		
Input Offset Voltage Change $ \Delta V_{IO} $	$I_{ABC} = 500\text{ }\mu\text{A}$ to $I_{ABC} = 5\text{ }\mu\text{A}$	—	0.1	3	mV	
Input Offset Current I_{IO}		—	0.12	0.6	μA	
Input Bias Current I_I		—	2	5	μA	
	$T_A = -55\text{ to }+125^\circ\text{C}$	—	—	8		
Forward Transconductance (large signal) g_m		7700	9600	12000	μmho	
	$T_A = -55\text{ to }+125^\circ\text{C}$	4000	—	—		
Peak Output Current $ I_{OM} $	$I_{ABC} = 5\text{ }\mu\text{A}$, $R_L = 0$	3	5	7	μA	
	$R_L = 0$	350	500	650		
	$R_L = 0$, $T_A = -55\text{ to }+125^\circ\text{C}$	300	—	—		
Peak Output Voltage:	Positive V^+_{OM}	$I_{ABC} = 5\text{ }\mu\text{A}$ $R_L = \infty$	12	13.8	—	V
	Negative V^-_{OM}		-12	-14.5	—	
	Positive V^+_{OM}	$R_L = \infty$	12	13.5	—	
	Negative V^-_{OM}		-12	-14.4	—	
Amplifier Supply Current I_A		0.8	1	1.2	mA	
Device Dissipation P_D		24	30	36	mW	
Input Offset Voltage Sensitivity:	Positive $\Delta V_{IO}/\Delta V^+$	—	—	150	$\mu\text{V/V}$	
	Negative $\Delta V_{IO}/\Delta V^-$	—	—	150		
Magnitude of Leakage Current	$I_{ABC} = 0$, $V_{TP} = 0$	—	0.08	5	nA	
	$I_{ABC} = 0$, $V_{TP} = 36\text{ V}$	—	0.3	5		
Differential Input Current	$I_{ABC} = 0$, $V_{DIFF} = 4\text{ V}$	—	0.008	5	nA	
Common-Mode Rejection Ratio CMRR		80	110	—	dB	
Common-Mode Input-Voltage Range V_{ICR}		12 to -12	13.6 to -14.6	—	V	
Input Resistance R_I		10	26	—	k Ω	

ELECTRICAL CHARACTERISTICS Typical Values Intended Only for Design Guidance

CA3080A CA3080AE CA3080AS

Amplifier Bias Voltage V_{ABC}		0.71	V
Slew Rate:	Maximum (uncompensated)	75	V/ μs
	Unity Gain (compensated) SR	50	
Open-Loop Bandwidth BWOL	—	2	MHz
Input Capacitance C_I	$f = 1\text{ MHz}$	3.6	pF
Output Capacitance C_O	$f = 1\text{ MHz}$	5.6	pF
Output Resistance R_O		.15	M Ω
Input-to-Output Capacitance C_{I-O}	$f = 1\text{ MHz}$	0.024	pF
Input Offset Voltage Temperature Drift $\Delta V_{IO}/\Delta T$	$I_{ABC} = 100\text{ }\mu\text{A}$, $T_A = -55\text{ to }+125^\circ\text{C}$	3	$\mu\text{V}/^\circ\text{C}$
Propagation Delay t_{PHL}, t_{PLH}	$I_{ABC} = 500\text{ }\mu\text{A}$	45	ns

Operational Amplifiers

CA3080, CA3080A Types

TYPICAL CHARACTERISTICS CURVES AND TEST CIRCUITS (Cont'd)

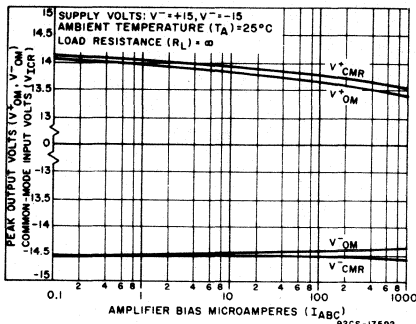


Fig. 7 — Peak output voltage as a function of amplifier bias current.

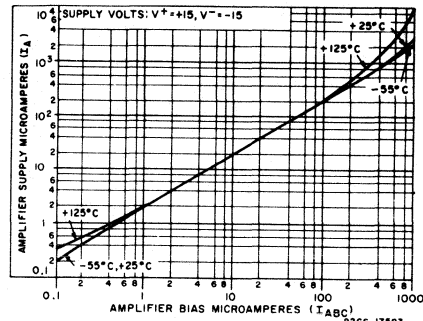


Fig. 8 — Amplifier supply current as a function of amplifier bias current.

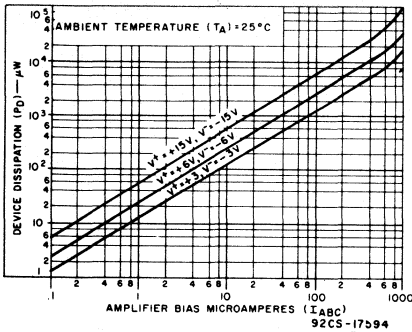


Fig. 9 — Total power dissipation as a function of amplifier bias current.

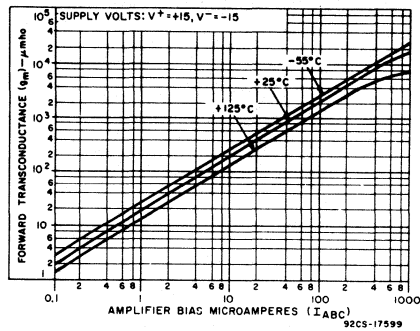


Fig. 10 — Transconductance as a function of amplifier bias current.

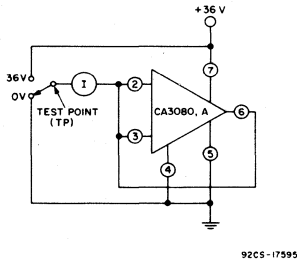


Fig. 11 — Leakage current test circuit.

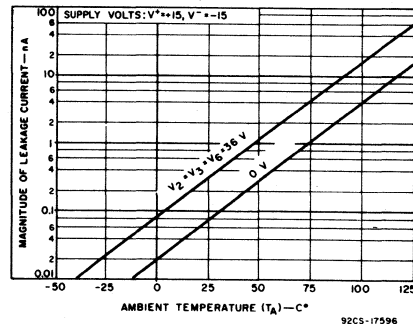


Fig. 12 — Leakage current as a function of temperature.

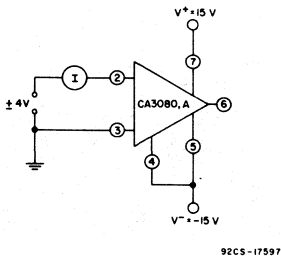


Fig. 13 — Differential input current test circuit.

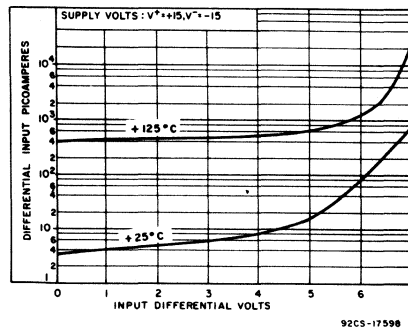


Fig. 14 — Input current as a function of input differential voltage.

Linear Integrated Circuits

CA3080, CA3080A Types

TYPICAL CHARACTERISTICS CURVES AND TEST CIRCUITS (Cont'd)

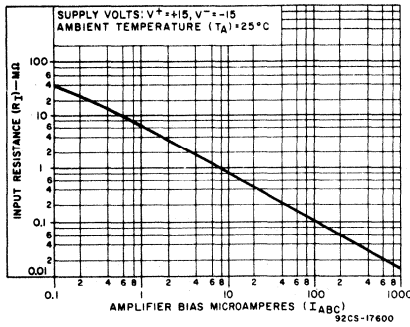


Fig. 15 - Input resistance as a function of amplifier bias current.

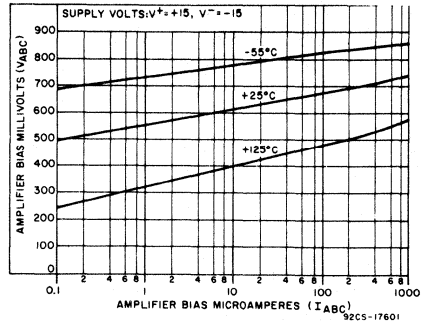


Fig. 16 - Amplifier bias voltage as a function of amplifier bias current.

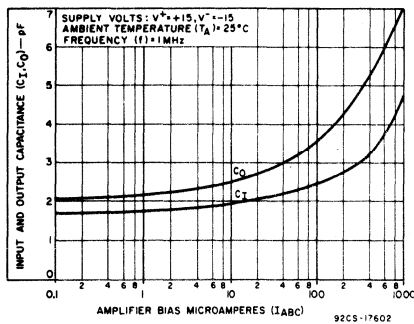


Fig. 17 - Input and output capacitance as a function of amplifier bias current.

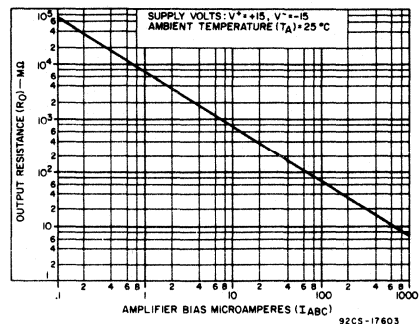


Fig. 18 - Output resistance as a function of amplifier bias current.

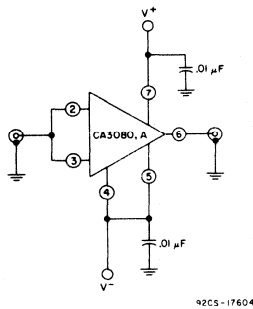


Fig. 19 - Input-to-output capacitance test circuit.

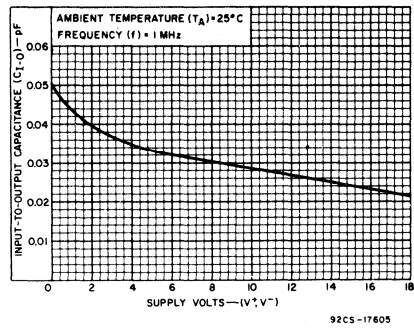


Fig. 20 - Input-to-output capacitance as a function of supply voltage.

APPLICATIONS

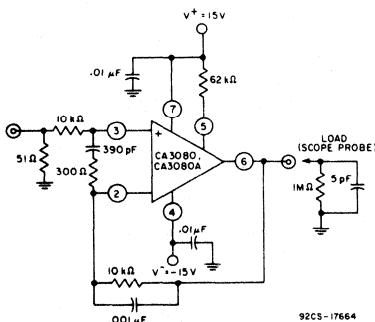
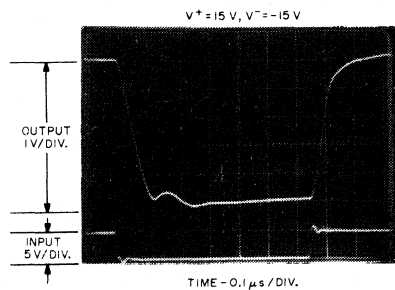


Fig. 21 - Schematic diagram of the CA3080 and CA3080A in a unity-gain voltage follower configuration and associated waveform.



92CS-24034

Operational Amplifiers

CA3080, CA3080A Types

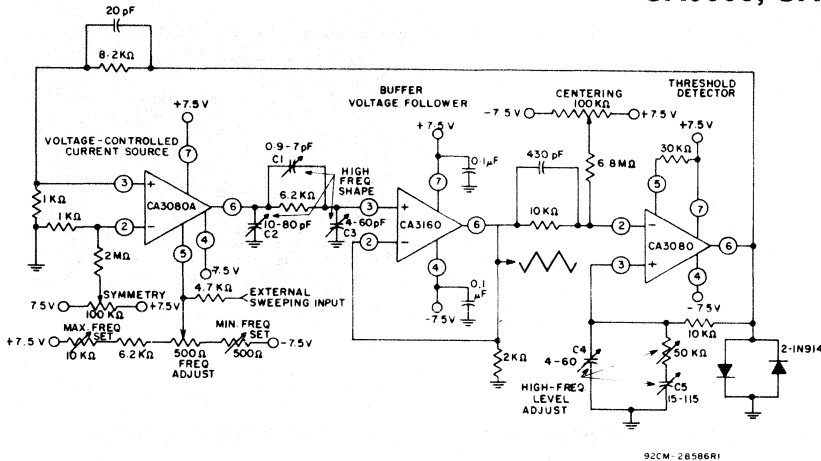
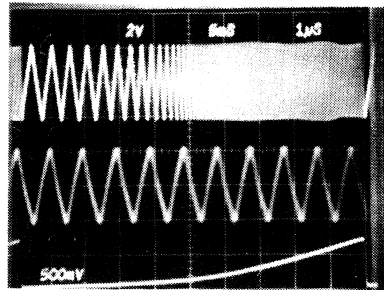
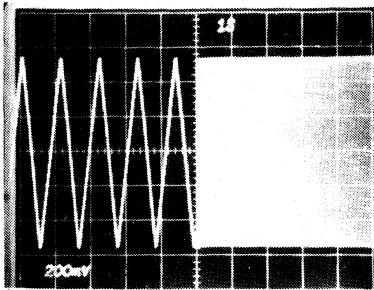


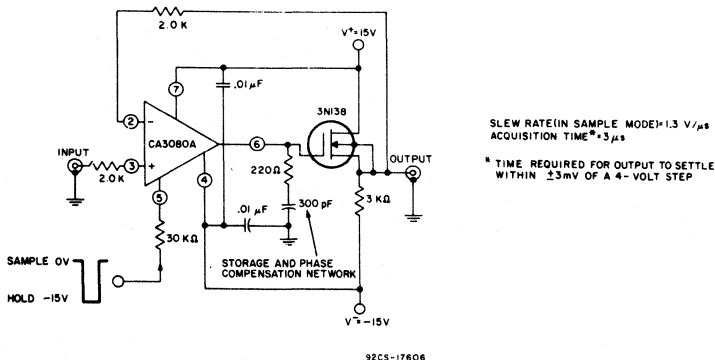
Fig.22 - 1,000,000/1 single-control function generator - 1 MHz to 1 Hz.



(a) - Two-tone output signal from the function generator. A square-wave signal modulates the external sweeping input to produce 1 Hz and 1 MHz, showing the 1,000,000/1 frequency range of the function generator.

(b) - Triple-trace of the function generator sweeping to 1 MHz. The bottom trace is the sweeping signal and the top trace is the actual generator output. The center trace displays the 1 MHz signal via delayed oscilloscope triggering of the upper swept output signal.

Fig.23 - Function generator dynamic characteristics waveforms.



SLEW RATE (IN SAMPLE MODE) = 1.3 V/μs
ACQUISITION TIME* = 3 μs

* TIME REQUIRED FOR OUTPUT TO SETTLE WITHIN ±3mV OF A 4-VOLT STEP

Fig.24 - Schematic diagram of the CA3080A in a sample-and-hold configuration.

Linear Integrated Circuits

CA3080, CA3080A Types

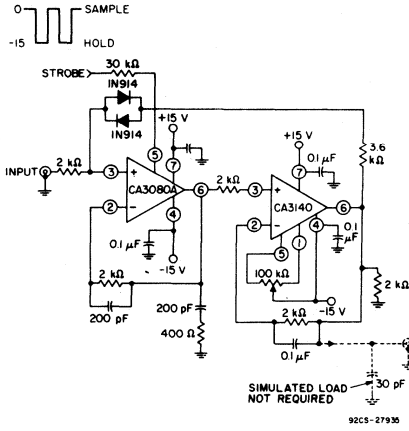
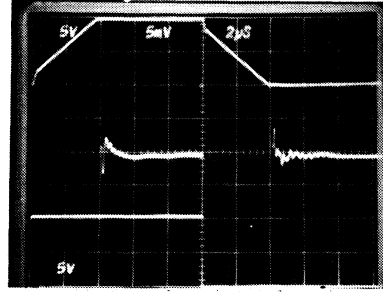


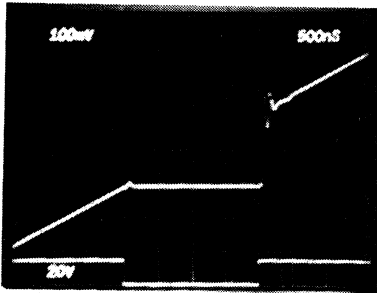
Fig.25 – Sample- and hold circuit.



LARGE-SIGNAL RESPONSE AND
SETTLING TIME
TOP TRACE: OUTPUT SIGNAL
(5 V/DIV. AND 2 μs/DIV.)
BOTTOM TRACE: INPUT SIGNAL
(5 V/DIV. AND 2 μs/DIV.)
CENTER TRACE: DIFFERENCE OF INPUT AND OUTPUT
SIGNALS THROUGH TEKTRONIX
AMPLIFIER 7A13
(5 mV/DIV. AND 2 μs/DIV.)

92CS-27664

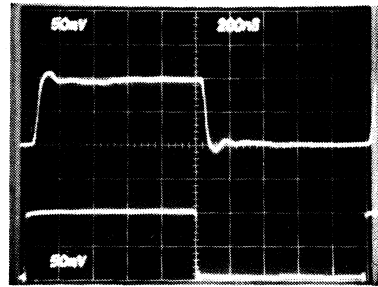
Fig.26 – Large-signal response and settling time for circuit shown in Fig.25.



SAMPLING RESPONSE
TOP TRACE: SYSTEM OUTPUT
(100 mV/DIV. AND 500 ns/DIV.)
BOTTOM TRACE: SAMPLING SIGNAL
(20 V/DIV. AND 500 ns/DIV.)

92CS-27885

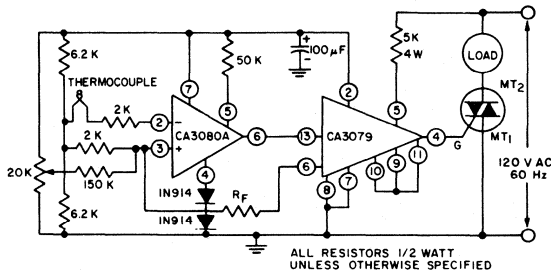
Fig.27 – Sampling response for circuit shown in Fig. 25.



TOP TRACE: OUTPUT
(50 mV/DIV. AND 200 ns/DIV.)
BOTTOM TRACE: INPUT
(50 mV/DIV. AND 200 ns/DIV.)

92CS-27883

Fig.28 – Input and output response for circuit shown in Fig. 25.



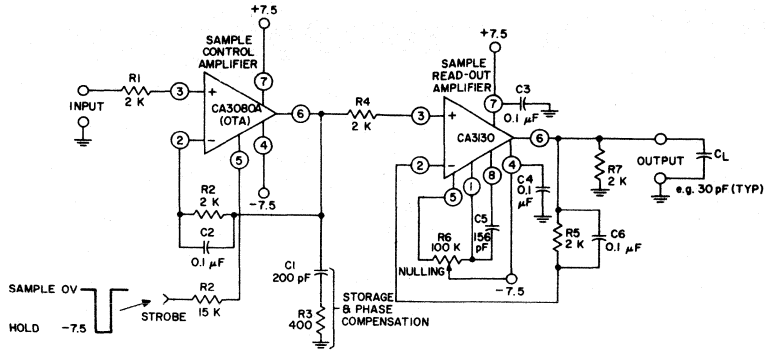
ALL RESISTORS 1/2 WATT
UNLESS OTHERWISE SPECIFIED

92CS-22619R1

Fig.29 – Thermocouple temperature control with CA3079 zero voltage switch as the output amplifier.

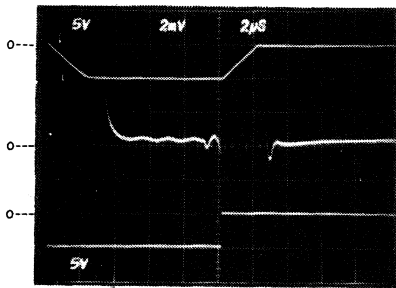
Operational Amplifiers

CA3080, CA3080A Types



92CM-27159R1

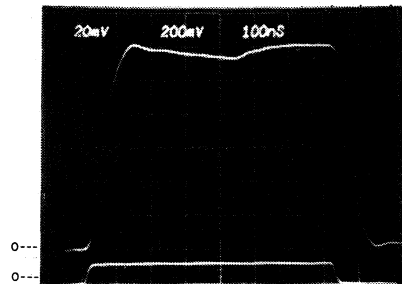
Fig.30 – Schematic diagram of the CA3080A in a sample-and-hold circuit with BiMOS output amplifier.



TOP TRACE: OUTPUT—5V/DIV. & 2 μs/DIV.
 CENTER TRACE: DIFFERENTIAL COMPARISON OF
 INPUT & OUTPUT—2 mV/DIV. & 2 μs/DIV.
 BOTTOM TRACE: INPUT—5 V/DIV. & 2 μs/DIV.

92CS-27161

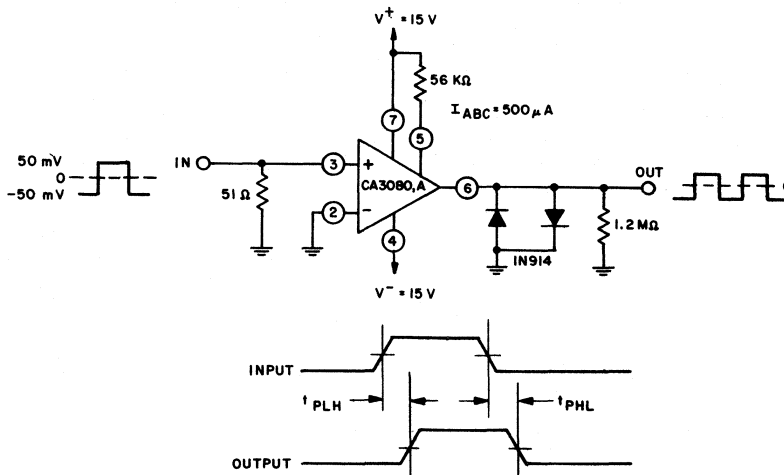
Fig.31 – Large-signal response for circuit shown in Fig. 30.



TOP TRACE: OUTPUT—20 mV/DIV. & 100 ns/DIV.
 BOTTOM TRACE: INPUT—200 mV/DIV. & 100 ns/DIV.

92CS-27160

Fig.32 – Small-signal response for circuit shown in Fig. 30.

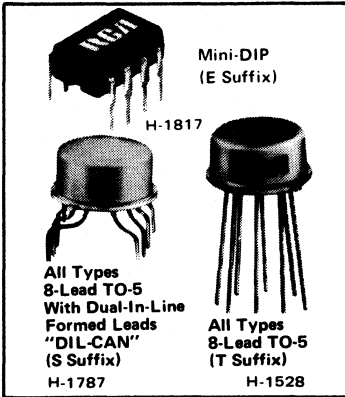


92CM-34766

Fig. 33 – Propagation delay test circuit and associated waveforms.

Linear Integrated Circuits

CA3440, CA3440A, CA3440B



Nanopower BiMOS Op Amp

Features:

- 300-nW (typ.) standby power at $V^+ = 5\text{ V}$
- Supply current, BW, slew rate programmable using external resistor
- 10-pA (typ.) input current
- 4.0 to 15-V supply
- Output drives typical bipolar-type loads
- Low-cost 8-lead Mini-DIP, TO-5

The RCA-CA3440B, CA3440A, and CA3440* are integrated circuit operational amplifiers that combine the advantages of MOS and bipolar transistors on a single monolithic chip.

The CA3440-series BiMOS Op Amp features gate-protected PMOS transistors in the input circuit to provide very-high-input impedance and very-low-input current (10 pA). These devices operate at total supply voltages from 4 to 15 volts and can be operated over the temperature range from -55°C to $+125^\circ\text{C}$. Their virtues are programmability and very low standby power consumption (300 nW). These operational amplifiers are internally phase-compensated to achieve stable operation in the unity-gain follower configuration. Terminals are also provided for use in applications requiring input offset-voltage nulling. The use of PMOS in the input stage results in common-mode input voltage capability down to 0.5 volts below the negative-supply terminal, an important attribute for single-supply applications. The output stage uses MOS complementary source-follower form which permits moderate load driving capability (10 K Ω) at very low total standby currents (50 nA).

The CA3440-series has the same 8-lead terminal pin-out used for "741" and other industry-standard op amps with two exceptions: terminals one and five must be connected to the negative supply or to a potentiometer if nulling is required. Terminal 8 must be programmed through an external resistor returned to the negative supply.

These devices are supplied in either the standard 8-lead TO-5 style package (T suffix), 8-lead dual-in-line formed-lead TO-5 style "DIL-CAN" package (S suffix), or in the 8-lead dual-in-line plastic package "Mini-DIP" (E suffix). They are also available in chip form (H suffix).

* Formerly Dev. Type No. TA10590.

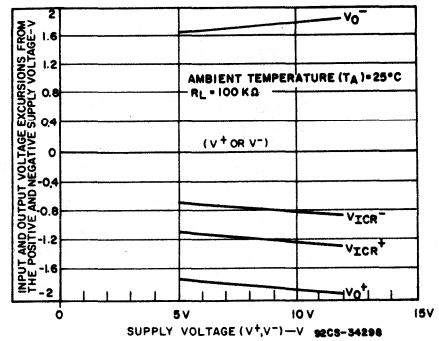


Fig. 1 - Output-voltage-swing and common-mode input-voltage range versus supply voltage.

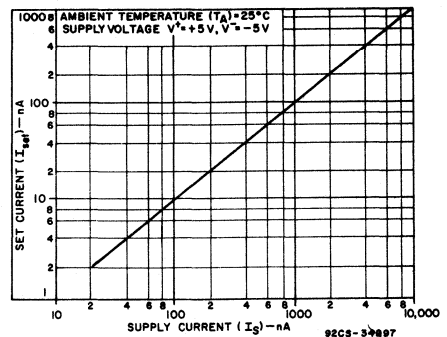


Fig. 2 - Set current versus supply current.

Operational Amplifiers

CA3440, CA3440A, CA3440B

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE		
(BETWEEN V ⁺ AND V ⁻ TERMINALS)	25 V
DIFFERENTIAL-MODE INPUT VOLTAGE	±9 V
COMMON-MODE DC INPUT VOLTAGE (V ⁺ +8 V) to (V ⁻ -0.5 V)	
INPUT-TERMINAL CURRENT	1 mA
DEVICE DISSIPATION:		
WITHOUT HEAT SINK —		
UP TO 55°C	630 mW
ABOVE 55°C	Derate linearly 6.67 mW/°C
WITH HEAT SINK —		
AT 125°C	418 mW
BELOW 125°C	Derate linearly 16.7 mW/°C
TEMPERATURE RANGE:		
OPERATING	-55 to +125°C
STORAGE	-65 to +150°C
OUTPUT SHORT-CIRCUIT DURATION	INDEFINITE
LEAD TEMPERATURE (DURING SOLDERING):		
AT DISTANCE 1/16 ± 1/32 IN. (1.59 ± 0.79 MM) FROM CASE FOR 10 SECONDS MAX.	+265°C

TYPICAL VALUES INTENDED ONLY FOR DESIGN GUIDANCE

CHARACTERISTIC	TEST CONDITIONS		CA3440B (T,S)	CA3440A	CA3440	UNITS
	V ⁺ =+5 V; V ⁻ =-5 V R _{SET} =10 MΩ; T _A =25°C					
Input Resistance, R _I			2	2	2	TΩ
Input Capacitance, C _T			3.5	3.5	3.5	pF
Output Resistance, R _O			450	450	450	Ω
Equivalent Input Noise Voltage, e _n	f= 1 kHz	R _S =100 Ω	110	110	110	nV/√Hz
	f=10 kHz		110	110	110	
Short-Circuit Current Source I _{OM} ⁺			15	15	15	mA
To Opposite Supply Sink I _{OM} ⁻			4.5	4.5	4.5	
Gain-Bandwidth Product, f _T			63	63	63	kHz
Slew Rate, SR			0.03	0.03	0.03	V/μs
Transient Response						
Rise Time, t _r	R _L = 10 kΩ		5.6	5.6	5.6	μs
Overshoot	C _L =100 pF		10	10	10	%

Linear Integrated Circuits

CA3440, CA3440A, CA3440B

ELECTRICAL CHARACTERISTICS FOR EQUIPMENT DESIGN

At $V^+ = +5\text{ V}$, $V^- = -5\text{ V}$, $T_A = 25^\circ\text{C}$ Unless Otherwise Specified, $R_{SET} = 10\text{ M}\Omega$

CHARACTERISTIC	LIMITS									UNITS
	CA3440B			CA3440A			CA3440			
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage, $ V_{IO} $	—	0.8	2	—	2	5	—	5	10	mV
Input Offset Current, $ I_{IO} $	—	2.5	10	—	2.5	20	—	2.5	30	pA
Input Current, $ I_I $	—	10	30	—	10	40	—	10	50	
Large-Signal Voltage Gain, AOL ($R_L = 10\text{ K}\Omega$)	32K	100K	—	10K	100K	—	10K	100K	—	V/V
	90	100	—	80	100	—	80	100	—	dB
Common-Mode Rejection Ratio, CMRR	75	90	—	70	80	—	70	80	—	dB
Common-Mode Input Voltage Range, V_{ICR}^+	+3.5	+3.7	—	+3.5	+3.7	—	+3.5	+3.7	—	V
V_{ICR}^-	-5.0	-5.3	—	-5.0	-5.3	—	-5.0	-5.3	—	
Power Supply Rejection Ratio, $\Delta V_{IO}/\Delta V$	—	20	180	—	32	320	—	32	320	$\mu\text{V}/\text{V}$
PSRR	75	94	—	70	90	—	70	90	—	dB
Maximum Output Voltage, V_{OM}^+	+3	+3.2	—	+3	+3.2	—	+3	+3.2	—	V
	V_{OM}^-	-3	-3.2	—	-3	-3.2	—	-3	-3.2	
Supply Current, I^+	—	10	17	—	10	17	—	10	17	μA
Device Dissipation, P_D	—	100	170	—	100	170	—	100	170	μW
Input Offset Voltage Temperature Drift, $\Delta V_{IO}/\Delta T$	—	4	—	—	4	—	—	4	—	$\mu\text{V}/^\circ\text{C}$

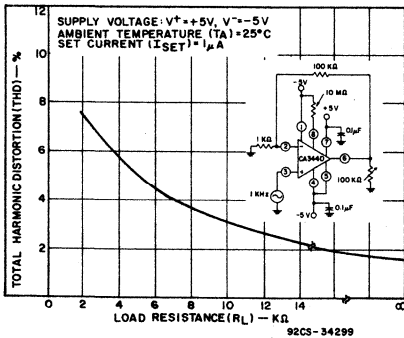


Fig. 3 - Total harmonic distortion percentage versus load resistance.

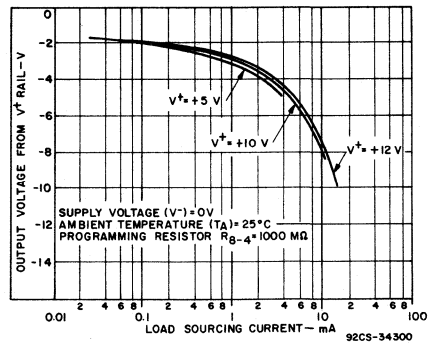


Fig. 4 - Output voltage versus sourcing load current.

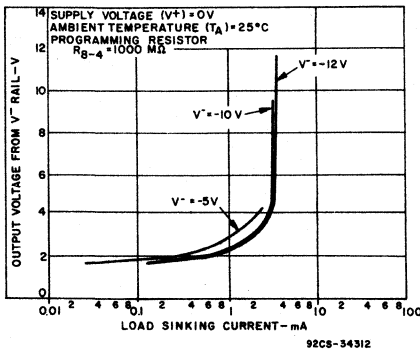


Fig. 5 - Output voltage versus sinking load current.

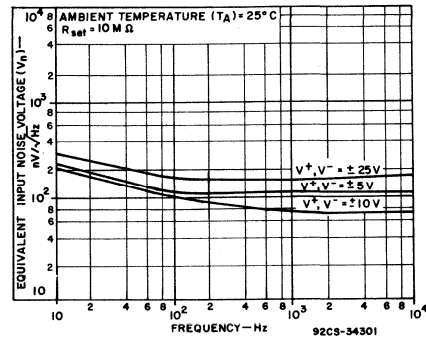


Fig. 6 - Input noise voltage versus frequency.

Operational Amplifiers

CA3440, CA3440A, CA3440B

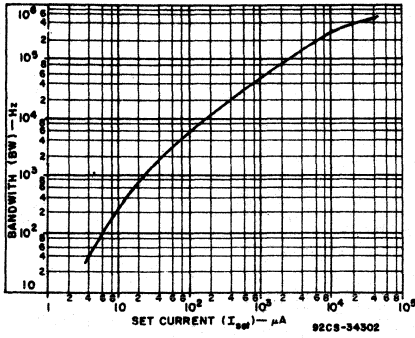


Fig. 7 - Bandwidth versus set current.

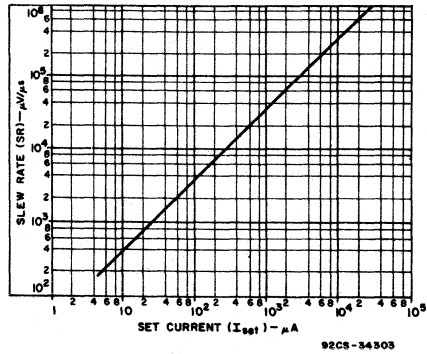


Fig. 8 - Slew rate versus set current.

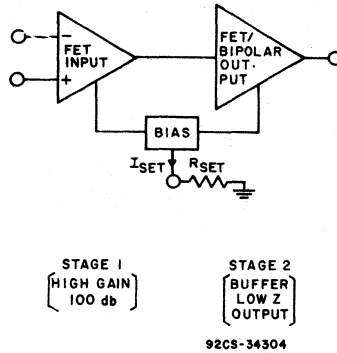


Fig. 9 - Nanopower op amp (supply current programmable using R_{SET}) 1-pA typical input bias current, 4.0 to 15-volt supply.

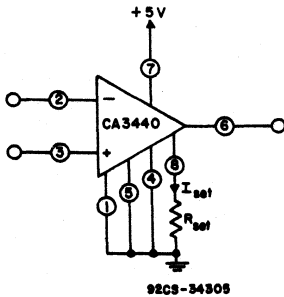


Fig. 10 - Nanopower op amp (usable standby power versus programming resistor R_{SET}).

As R_{SET} is increased, I_{SET} and the standby power decrease while the BW/SR also decreases.

Operating at a +5 V single supply, the CA3440 exhibits the following characteristics:

R_{SET}	Standby Power	BW	SR
1 M Ω	250 μ W	164 kHz	0.17 V/ μ s
10 M Ω	25 μ W	27 kHz	0.017 V/ μ s
100 M Ω	2.5 μ W	2.6 kHz	.0017 V/ μ s
1000 M Ω	250 nW	78 Hz	0.00017 V/ μ s

The CA3440 is pin-compatible with the 741 except that pins 1 and 5 (typical negative nulling pins) must be connected either directly to pin 4 or to a negative nulling potentiometer. In addition, pin 8, the I_{SET} terminal, must be returned to either ground or $-V$ via R_{SET} .

Linear Integrated Circuits

CA3440, CA3440A, CA3440B

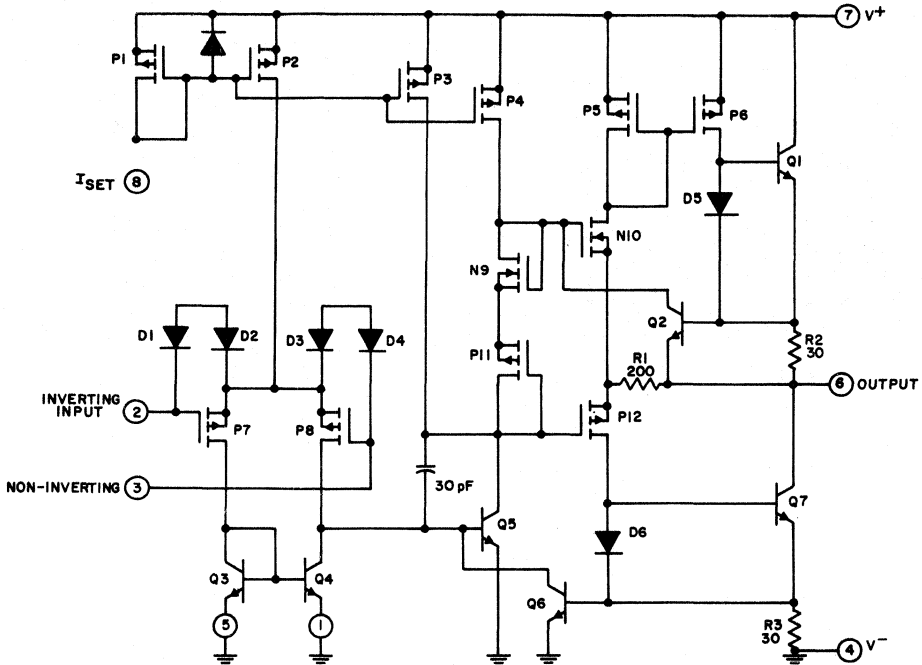
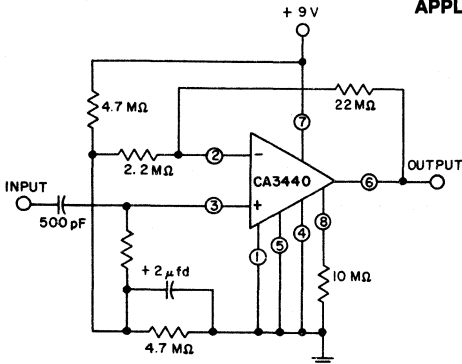


Fig. 11 - Schematic diagram for CA3440.

92CM-34308

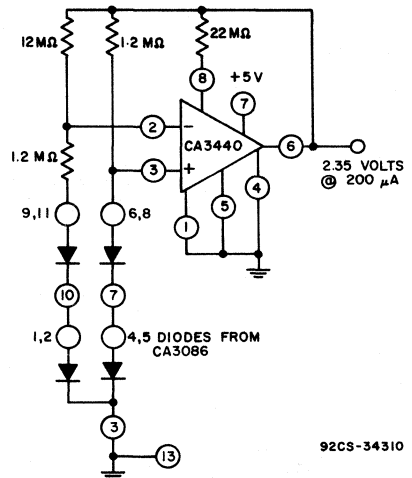
APPLICATIONS CIRCUITS



$R_{in} > 20 \text{ M}\Omega$
 STAND-BY POWER = $90 \mu\text{W}$
 GAIN = 20 db
 BW = 20-Hz TO 3-KHz
 SR = $0.016 \text{ V}/\mu\text{s}$

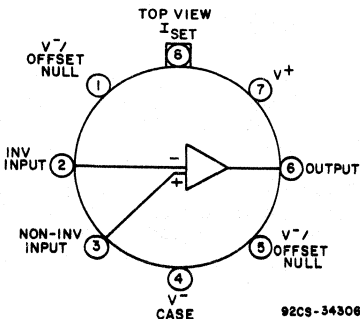
92CS-34309

Fig. 12 - High-input impedance amplifier.



92CS-34310

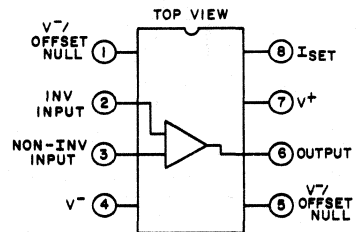
Fig. 13 - Micropower bandgap reference.



92CS-34306

S and T Suffixes

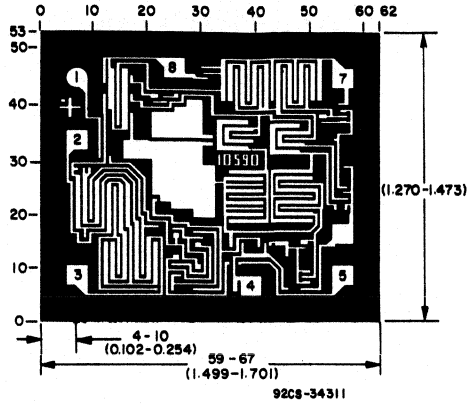
Functional diagrams for CA3440 series.



92CS-34307

E Suffix

CA3440, CA3440A, CA3440B

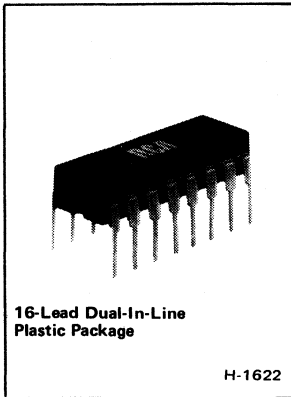


Dimensions and pad layout for CA3440H.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

The layout represents a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

CA3280, CA3280A



Dual Variable Operational Amplifiers

Features:

- Low initial input-offset voltage: 500 μV max. (CA3280A)
- Low offset-voltage change versus I_{ABC} : < 500 μV typ. for all types
- Low offset-voltage drift: 5 $\mu\text{V}/\text{C}$ max. (CA3280A)

The RCA-CA3280 and CA3280A types consist of two variable operational amplifiers that are designed to substantially reduce the initial input offset voltage and the offset-voltage variation with respect to changes in programming current. This design results in reduced "AGC thump," an objectionable characteristic of many AGC systems. Interdigitation, or crosscoupling, of critical portions of the circuit reduces the amplifier dependence upon thermal and processing variables.

The CA3280 has all the generic characteristics of an operational voltage amplifier

- Excellent matching of the two amplifiers for all characteristics
- Internal current-driven linearizing diodes reduce the external input current to an offset component
- Differential amplifier emitters brought out for use in emitter-coupled dual-differential amplifier applications
- Low noise: 8 $\text{nV}/\sqrt{\text{Hz}}$ @ 1 kHz typ.
- Low distortion: 0.4% THD typ.
- Two modes of gain control

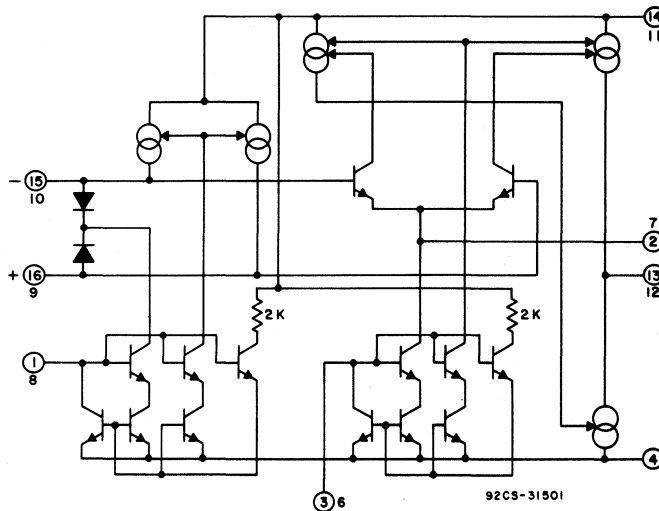


Fig. 1 - Functional diagram of 1/2 CA3280.

CA3280, CA3280A

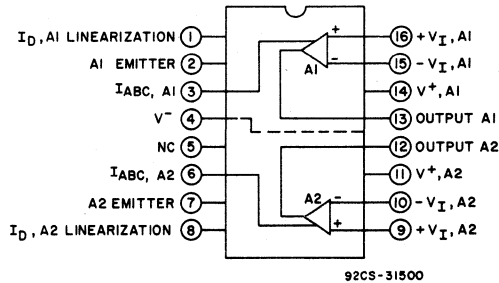
except that the forward transfer characteristic is best described by transconductance rather than voltage gain, and the output is current, not voltage. The magnitude of the output current is equal to the product of transconductance and the input voltage. This type of operational transconductance amplifier was first introduced by RCA in 1969*, and it has since gained wide acceptance as a gateable, gain-controlled building block for instrumentation and audio applications, such as linearization of transducer outputs, standardization of widely changing signals for data processing, multiplexing, instrumentation amplifiers operating from the nanopower range to high current and high-speed comparators.

The CA3280 and CA3280A are supplied in the 16-lead dual-in-line plastic package (E suffix). The operating-temperature ranges are -55 to $+125^{\circ}\text{C}$ for the CA3280A and 0 to $+70^{\circ}\text{C}$ for the CA3280. The CA3280 is also supplied as a hermetic (H suffix).

Applications:

- Voltage-controlled amplifiers
- Voltage-controlled filters
- Voltage-controlled oscillators
- Multipliers
- Demodulators
- Sample and hold
- Instrumentation amplifiers
- Function generators
- Triangle wave-to-sine wave converters
- Comparators
- Audio preamplifiers

* "OTA Obsoletes Op Amp," by C.F. Wheatley and H.A. Wittlinger, NEC Proceedings, December, 1969.



Terminal Assignment

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE (BETWEEN V^+ AND V^- TERMINALS)	36 V
DIFFERENTIAL INPUT VOLTAGE	± 5 V
DC INPUT VOLTAGE RANGE	V^+ to V^-
INPUT SIGNAL CURRENT AT $I_D = 0$	100 μA
AMPLIFIER BIAS CURRENT	10 mA
OUTPUT SHORT CIRCUIT DURATION*	Indefinite
LINEARIZING DIODE BIAS CURRENT, I_D	.5 mA
PEAK INPUT CURRENT WITH LINEARIZING DIODE	$\pm I_D$
POWER DISSIPATION, P_D :	
Either Amplifier	600 mW
Total Package	750 mW
Above 55°C	Derate linearly at 6.67 mW/ $^{\circ}\text{C}$
AMBIENT TEMPERATURE RANGE, T_A :	
Operating:	
CA3280	0 to $+70^{\circ}\text{C}$
CA3280A	-55 to $+125^{\circ}\text{C}$
Storage, All Types	
	-65 to $+150^{\circ}\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 \pm 1/32 in. (1.59 \pm 0.79 mm)	
from case for 10 sec. max.	$+265^{\circ}\text{C}$

* Short circuit may be applied to ground or to either supply.

Linear Integrated Circuits

CA3280, CA3280A

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V^\pm = 15\text{ V}$ (Unless Otherwise Stated) For Equipment Design

CHARACTERISTIC	TEST CONDITIONS	LIMITS						UNITS
		CA3280			CA3280A			
		Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage, V_{IO}	$I_{ABC}=1\text{ mA}$	—	—	3	—	—	0.5	mV
	$I_{ABC}=100\mu\text{A}$	—	0.7	3	—	0.25	0.5	
	$I_{ABC}=10\mu\text{A}$	—	—	3	—	—	0.5	
	$I_{ABC}=1\text{ mA to }10\mu\text{A}$ $T_A=\text{full temp. range}$	—	0.8	4	—	0.8	1.5	
Input Offset Voltage Change, $ \Delta V_{IO} $	$I_{ABC}=1\mu\text{A to }1\text{ mA}$	—	0.5	1	—	0.5	1	mV
	$I_{ABC}=100\mu\text{A}$ $T_A=\text{full temp. range}$	—	5	—	—	3	5	$\mu\text{V}/^\circ\text{C}$
Amplifier Bias Voltage, V_{ABC}	$I_{ABC}=100\mu\text{A}$	—	1.2	—	—	1.2	—	V
Peak Output Voltage: Positive VOM ⁺ Negative VOM ⁻	$I_{ABC}=500\mu\text{A}$	12	13.7	—	12.5	13.7	—	V
		12	-14.3	—	-13.3	-14.3	—	
	$I_{ABC}=5\mu\text{A}$	12	13.9	—	12.5	13.9	—	
		12	-14.5	—	-13.5	-14.5	—	
Common-Mode Input Voltage Range, V_{ICR}	$I_{ABC}=100\mu\text{A}$	-13	—	13	-13	—	13	V
Noise Voltage, e_N : 10 Hz 1 kHz 10 kHz	$I_{ABC}=500\mu\text{A}$	—	20	—	—	20	—	$\text{nV}/\sqrt{\text{Hz}}$
		—	8	—	—	8	—	$\mu\text{V}/\sqrt{\text{Hz}}$
		—	7	—	—	7	—	$\text{nV}/\sqrt{\text{Hz}}$
Input Offset Current, I_{IO}	$I_{ABC}=500\mu\text{A}$	—	0.3	0.7	—	0.3	0.7	μA
Input Bias Current, I_{IB}	$I_{ABC}=500\mu\text{A}$	—	1.8	5	—	1.8	5	μA
	$I_{ABC}=500\mu\text{A}$ $T_A=\text{full temp. range}$	—	3	8	—	3	8	
Peak Output Current: Source IOM ⁺ Sink IOM ⁻ Source IOM ⁺ Sink IOM ⁻ Sink and Source, IOM ⁻ , IOM ⁺	$I_{ABC}=500\mu\text{A}$	350	410	650	350	410	650	μA
		-350	-410	-650	-350	-410	-650	
	$I_{ABC}=5\mu\text{A}$	3	4.1	7	3	4.1	7	
		-3	-4.1	-7	-3	-4.1	-7	
	$I_{ABC}=500\mu\text{A}$ $T_A=\text{full temp. range}$	350	450	550	350	450	550	
Linearization Diodes: Dynamic Impedance Offset Current	$I_D = 100\mu\text{A}$	—	700	—	—	700	—	Ω
		—	10	—	—	10	—	μA
$I_D=10\mu\text{A}$	—	0.5	1	—	0.5	1		

ELECTRICAL CHARACTERISTICS (Cont'd)

CHARACTERISTIC	TEST CONDITIONS	LIMITS						UNITS
		CA3280			CA3280A			
		Min.	Typ.	Max.	Min.	Typ.	Max.	
Diode Network Supply Current	$I_{ABC}=100\mu A$	250	400	800	250	400	800	μA
Amplifier Supply Current (Per amplifier)	$I_{ABC}=500\mu A$	—	2	2.4	—	2	2.4	mA
Amplifier Output Leakage Current, I_{OL}	$I_{ABC}=0, V_O=0V$	—	0.015	0.1	—	0.015	0.1	nA
	$I_{ABC}=0, V_O=30V$	—	0.15	1	—	0.15	1	
Common-Mode Rejection Ratio, CMRR	$I_{ABC}=100\mu A$	80	100	—	94	100	—	dB
Power-Supply Rejection Ratio, PSRR	$I_{ABC}=100\mu A$	86	105	—	94	105	—	dB
Open-Loop Voltage Gain, A_{OL}	$I_{ABC}=100\mu A, R_L=\infty,$	94	100	—	94	100	—	dB
	$V_O=20 V_{p-p}$	50K	100K	—	50K	100K	—	
Forward Transconductance:	Large Signal, G_m	—	0.8	1.2	—	0.8	1.2	mmho
	Small Signal, gm	—	16	22	—	16	22	
Input Resistance, R_I	$I_{ABC}=10\mu A$	0.5	—	—	0.5	—	—	$M\Omega$
Channel Separation	$f=1 kHz$	—	94	—	—	94	—	dB
Open-Loop Total Harmonic Distortion	$f=1 kHz, I_{ABC}=1.5 mA, R_I=15k\Omega, V_O=20 V_{p-p}$	—	0.4	—	—	0.4	—	%
Bandwidth	$I_{ABC}=1mA, R_L=100\Omega$	—	9	—	—	9	—	MHz
Slew Rate, SR: Open Loop	$I_{ABC}=1mA$	—	125	—	—	125	—	V/ μs
Capacitance:	Input, C_I	—	4.5	—	—	4.5	—	pF
	Output, C_O	—	7.5	—	—	7.5	—	
Output Resistance, R_O	$I_{ABC}=100\mu A$	—	63	—	—	63	—	$M\Omega$

Figs. 2 and 3 show the equivalent circuits for the current source and linearization diodes in the CA3280. The current through the linearization network is approximately equal to the programming current. There are several advantages to driving these diodes with a current source. First, only the offset current from the biasing network flows through the input resistor. Second, another input is provided to extend the gain control dynamic range. And third, the input is truly differential and can accept signals within the common-mode range of the CA3280.

The structure of the variable operational amplifier eliminates the need for matched resistor networks in differential to single-ended converters, as shown in Fig. 4. A matched resistor network requires ratio matching of 0.01% or trimming for 80 dB of common-mode rejection. The CA3280, with its excellent common-mode rejection ratio, is capable of converting a small ($\pm 25 mV$) differential input signal to a single-ended output without the need for a matched resistor network.

Linear Integrated Circuits

CA3280, CA3280A

Fig. 5 shows the CA3280 in a typical gain-control application. The input-signal range as a function of distortion at various levels of linearization diode current is shown in Fig. 6. This curve shows only the AGC capability of the diode network, but gain control can also be performed with the amplifier bias current (I_{ABC}). With no diode bias current, the gain is merely gmR_L . For example, with an I_{ABC} of 1 mA, the gm is approximately 16 mmhos. With the CA3280 operating into a 5 k Ω resistor, the gain is 80.

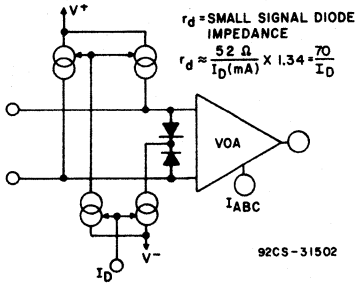


Fig. 2 - VOA showing linearization diodes and current drive.

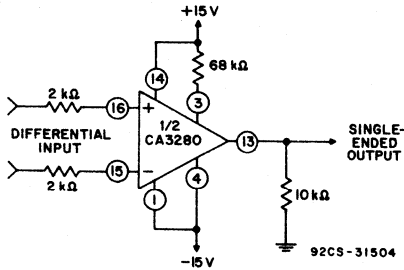


Fig. 4 - Differential to single-ended converter.

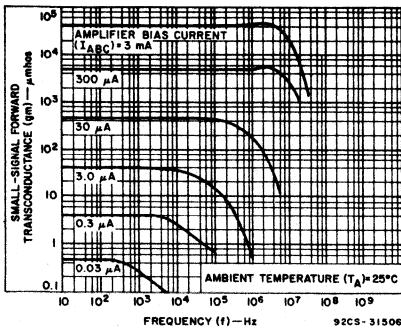


Fig. 6 - Amplifier gain as a function of frequency.

The need for external buffers can be eliminated by the use of low-value load resistors, but the resulting increase in the required amplifier bias current reduces the input impedance of the CA3280. The linearization diode impedance also decreases as the diode bias current increases, which further loads the input. The diodes, in addition to acting as a linearization network, also operate as an additional attenuation system to accommodate input signals in the volt range when they are applied through appropriate input resistors.

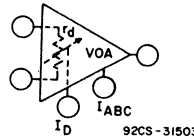


Fig. 3 - Block diagram of linearized VOA.

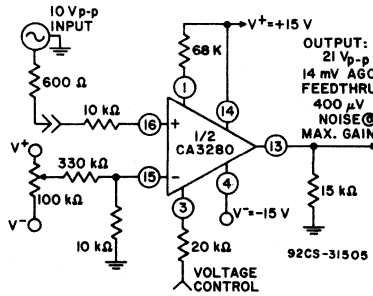


Fig. 5 - Typical gain control circuit.

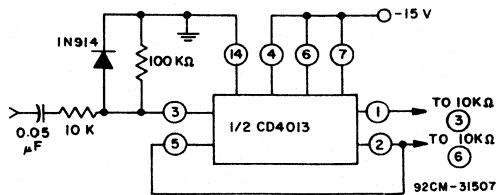
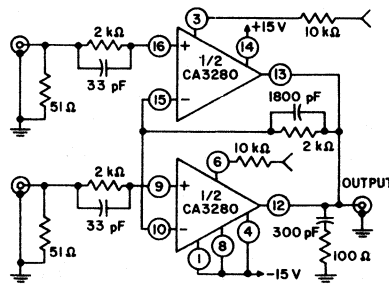


Fig. 7 - Two-channel linear multiplexer.

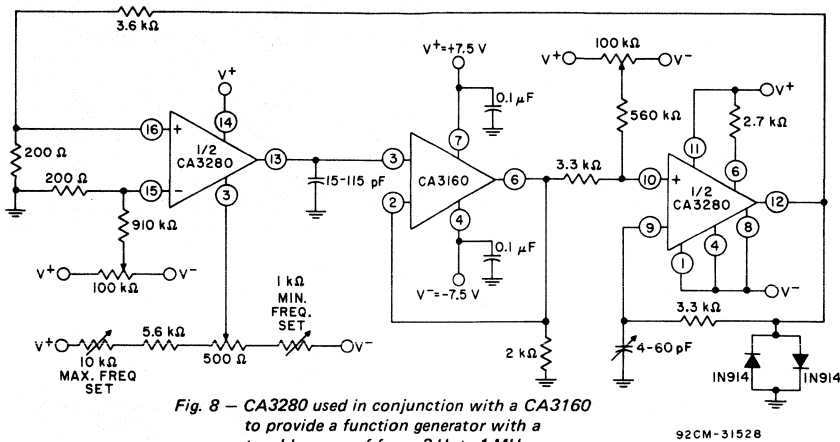


Fig. 8 — CA3280 used in conjunction with a CA3160 to provide a function generator with a tunable range of from 2 Hz to 1 MHz.

Fig. 9 shows a triangle wave-to-sine wave converter using the CA3280. Two 100KΩ resistors are connected between the differential amplifier emitters and V⁺ to reduce

the current flow through the differential amplifier. This allows the amplifier to fully cut off during peak input signal excursions. THD is approximately 0.37% for this circuit.

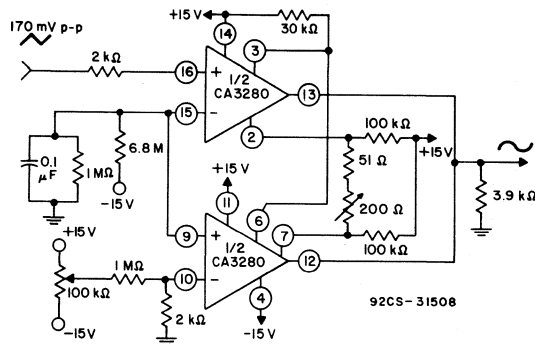


Fig. 9 — Triangle wave-to-sine wave converter.

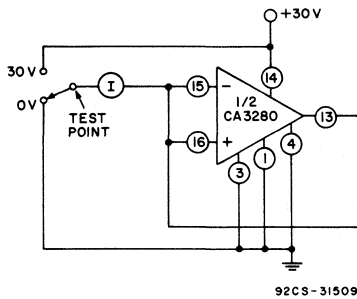


Fig. 10 — Leakage current test circuit.

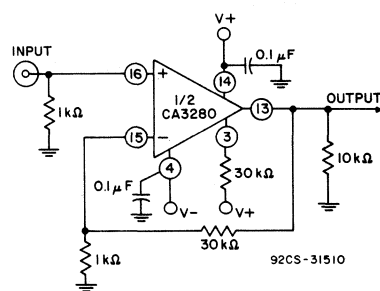
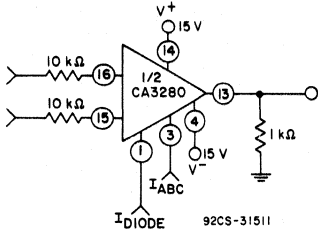


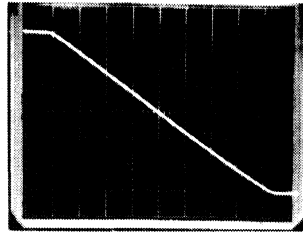
Fig. 11 — Channel separation test circuit.

Linear Integrated Circuits

CA3280, CA3280A

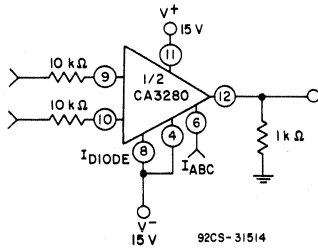


a) With diode programming terminal active

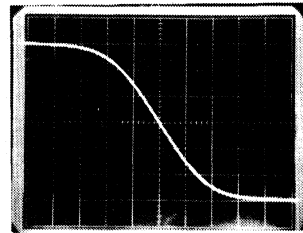


$I_{abc} = 650 \mu\text{A}$
 $I_D = 200 \mu\text{A}$
 VERT = $200 \mu\text{A}/\text{DIV}$
 HOR = 1 V/DIV

92CS-31512



b) With diode programming terminal cut-off



$I_{abc} = 650 \mu\text{A}$
 $I_D = 0$
 VERT = $200 \mu\text{A}/\text{DIV}$
 HOR = 25 mV/DIV

92CS-31513

Fig. 12 - CA3280 transfer characteristics.

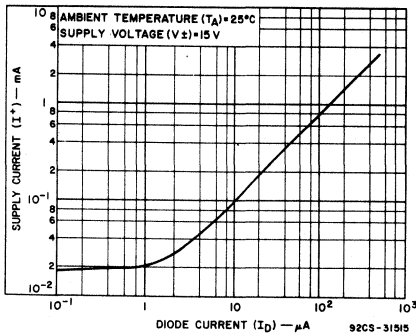


Fig. 13 - Supply current as a function of diode current.

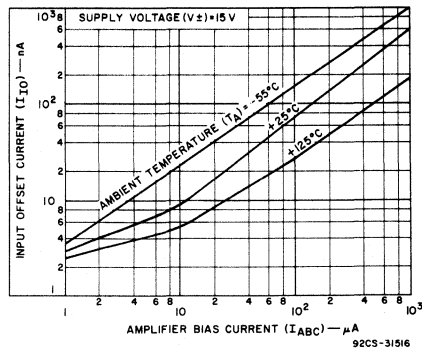


Fig. 14 - Input offset current as a function of amplifier bias current.

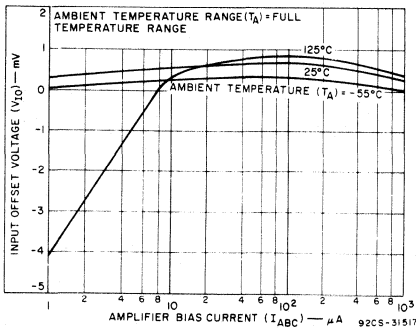


Fig. 15 - Input offset voltage as a function of amplifier bias current.

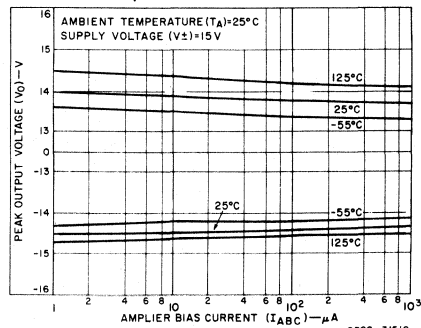


Fig. 16 - Peak output voltage as a function of amplifier bias current.

Operational Amplifiers

CA3280, CA3280A

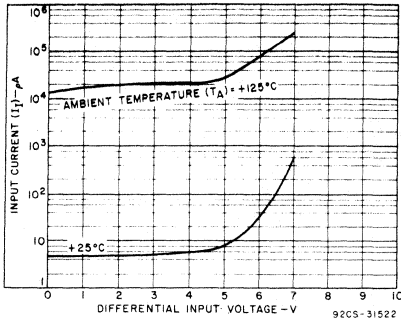


Fig. 17 — Input current as a function of input differential voltage.

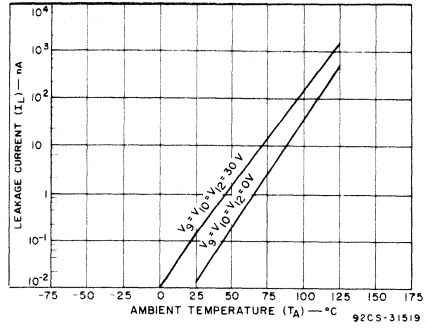


Fig. 18 — Leakage current as a function of temperature.

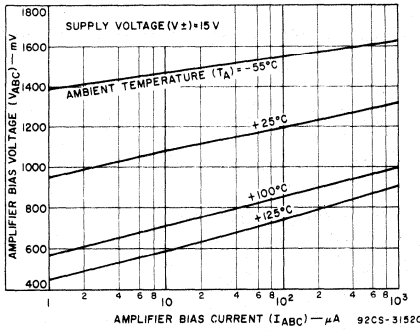


Fig. 19 — Amplifier bias voltage as a function of amplifier bias current.

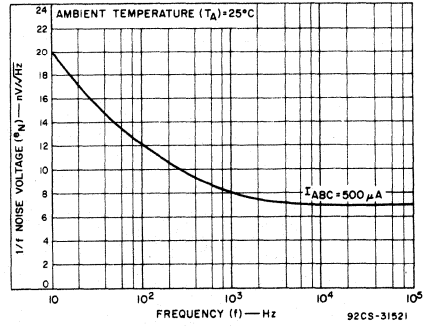


Fig. 20 — 1/f noise as a function of frequency.

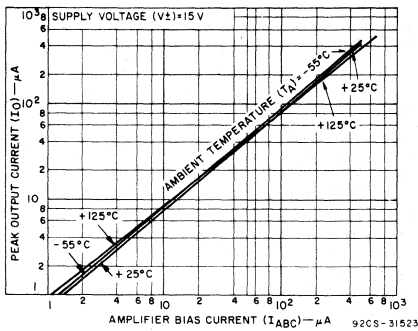


Fig. 21 — Peak output current as a function of amplifier bias current.

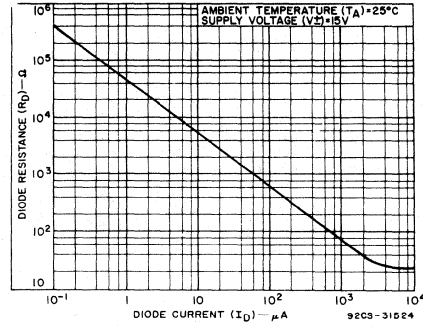


Fig. 22 — Diode resistance as a function of diode current.

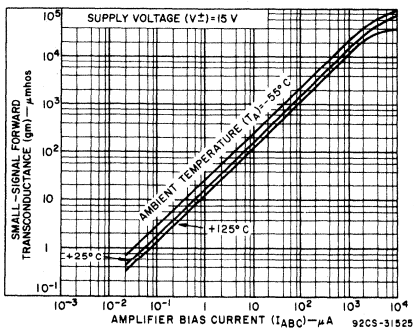


Fig. 23 — Amplifier gain as a function of amplifier bias current.

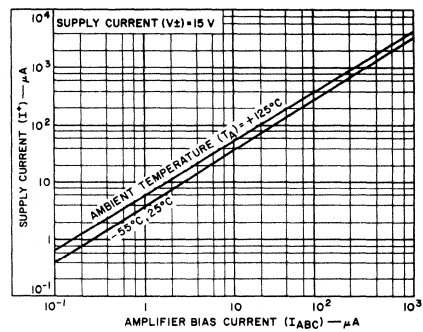


Fig. 24 — Supply current as a function of amplifier bias current.

Linear Integrated Circuits

CA3280, CA3280A

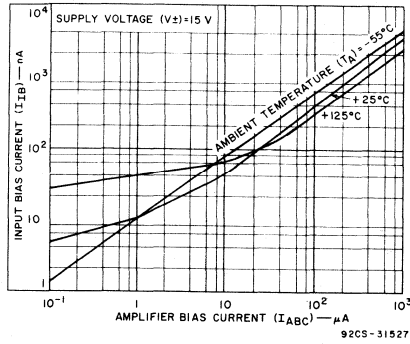
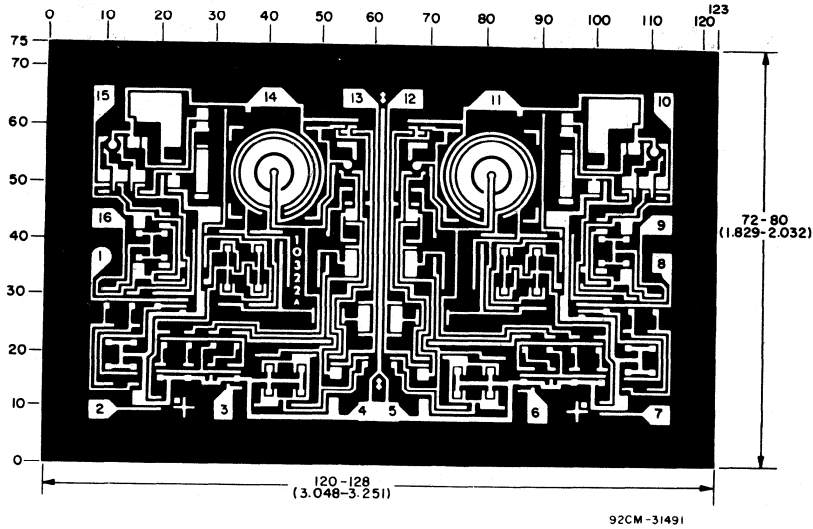


Fig. 25 — Input bias current as a function of amplifier bias current.



Dimensions and pad layout for CA3280H.

The photographs and dimensions represent a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

Voltage Comparators

Technical Data

Single Unit	Page
CA311	270
CA3098+	278
CA3099+	285

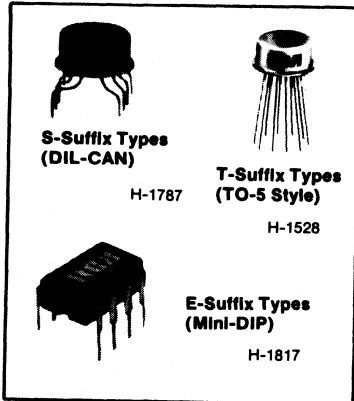
Dual Unit	Page
CA3290*	291

Quad Unit	Page
CA139	301
CA239	301
CA339	301

+Programmable

*BIMOS types

CA311



Voltage Comparator

For Commercial and Industrial Applications

Features:

- Single- or dual-supply operation
- Power consumption - 135 mW at ± 15 V
- Strobe capability
- Low input-offset current - 6 nA (typ.)
- Differential input-voltage range - ± 30 V
- Directly interchangeable with National Semiconductor LM311 Series

Applications:

- Multivibrators
- Positive and negative peak detectors
- Crystal oscillators
- Zero-crossing detectors
- Solenoid, relay, and lamp drivers

The RCA CA311 is a monolithic voltage comparator that operates from dual supplies up to ± 15 V, or from single supplies down to 5 V. This single supply capability makes the outputs of these devices compatible with RTL, DTL, TTL, and MOS circuits. In addition they can drive lamps or relays, and switch voltages up to 40 V at currents as high as 50 mA.

The inputs and outputs of the CA311 can be isolated from system ground, allowing the output to drive loads referred to ground V^+ , or V^- .

The CA311 is available in 8-lead TO-5 style packages with standard leads (T suffix), dual-in-line formed leads ("DIL-CAN", S suffix), 8-lead dual-in-line plastic package ("MINI-DIP", E suffix), and in chip form (H suffix).

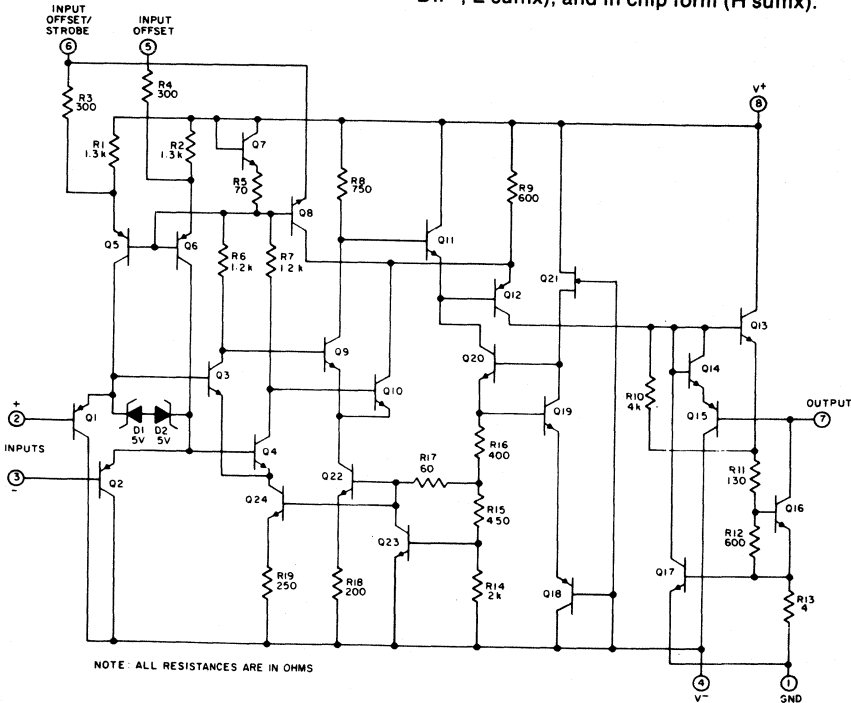


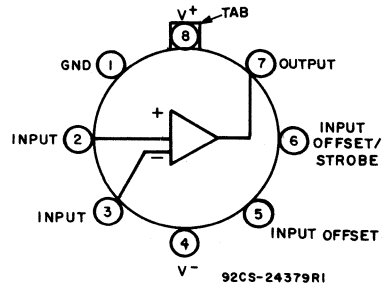
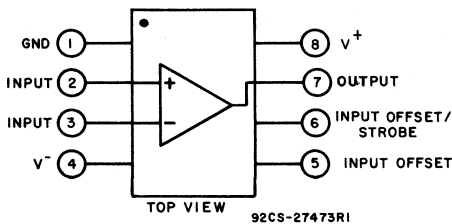
Fig. 1 - Schematic diagram of CA311.

Maximum Ratings, Absolute Maximum Values at $T_A = 25^\circ\text{C}$:

DC SUPPLY VOLTAGE (between V^+ and V^- terminals)	36 V
DC INPUT VOLTAGE*	± 15 V
DIFFERENTIAL INPUT VOLTAGE	± 30 V
OUTPUT TO NEGATIVE SUPPLY VOLTAGE (V_7-4)	40 V
GROUND TO NEGATIVE SUPPLY VOLTAGE (V_1-4)	30 V
OUTPUT SHORT-CIRCUIT DURATION	10 s
DEVICE DISSIPATION:	
UP TO $T_A = 25^\circ\text{C}$	500 mW
Above $T_A = 25^\circ\text{C}$	derate linearly at 6.67 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:	
Operating	0 to $+70^\circ\text{C}$ †
Storage	-65 to $+150^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 \pm 1/32 inch (1.59 \pm 0.79 mm) from case for 10 seconds max.	$+265^\circ\text{C}$

*This rating applies for ± 15 V supplies. The positive input-voltage limit is 30 V above the negative supply. The negative input-voltage limit is equal to the negative supply voltage or 30 V below the positive supply. The negative input-voltage limit is equal to the negative supply voltage or 30 V below the positive supply, whichever is less.

†Types CA311 E, S, and T can be operated over the temperature range of -55 to $+125^\circ\text{C}$, although the published limits for certain electrical specifications apply only over the temperature range of 0 to 70°C .



FUNCTIONAL DIAGRAM FOR PLASTIC PACKAGE.

FUNCTIONAL DIAGRAM FOR TO-5 STYLE PACKAGE.

TYPICAL CHARACTERISTICS

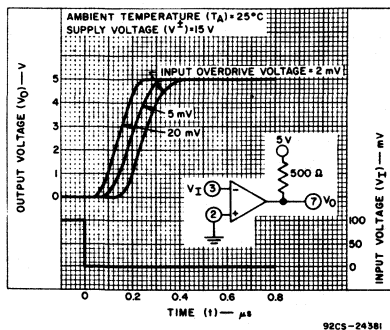


Fig. 2 - Response time for various input overdrive voltages - positive input.

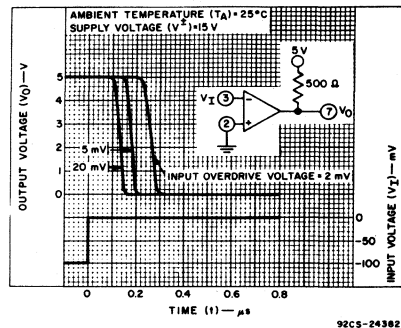


Fig. 3 - Response time for various input overdrive voltages - negative input.

Linear Integrated Circuits

CA311

ELECTRICAL CHARACTERISTICS

CHARACTERISTICS		TEST CONDITIONS		LIMITS			UNITS
		SUPPLY VOLTAGE (V±) = 15V UNLESS OTHERWISE SPECIFIED		CA311			
				MIN.	TYP.	MAX.	
Input Offset Voltage	V _{io}	R _s ≤ 5 kΩ, Note 2	T _A = 25°C	—	2	7.5	mV
			Note 1	—	—	10	
Saturation Voltage		V _i ≤ -10 mV, I _o = 50 mA	T _A = 25°C	—	0.75	1.5	V
			Note 1	—	0.23	0.4	
Input Voltage Range	V _{IPP}		Note 1	—	±14	—	V
Input Offset Current	I _{io}	Note 2	T _A = 25°C	—	6	50	nA
			Note 1	—	—	70	
Input Bias Current	I _{IB}	Note 2	T _A = 25°C	—	100	250	nA
			Note 1	—	—	300	
Positive Supply Current	I ⁺		T _A = 25°C	—	5.1	7.5	mA
Negative Supply Current	I ⁻		T _A = 25°C	—	4.1	5	mA
Output Leakage Current		V _i ≥ 10 mV, V _o = 35 V	T _A = 25°C	—	—	50	nA
Strobe on Current			T _A = 25°C	—	3	—	mA
Voltage Gain, A			T _A = 25°C	40	200	—	V/mV
Response Time		100 mV Input Step with 5 mV Overdrive Voltage	T _A = 25°C	—	200	—	ns
Input Voltage Range			T _A = 25°C	-14.5	13.8- -14.7	13	V

Note 1: Ambient temperature (T_A) over applicable operating temperature of 0 to +70°C.

Note 2: The input offset characteristics given are the values required to drive the output to within 1 V of either supply with a 1 mA load. These characteristics define an error band which takes into account the worst-case effects of voltage gain and input impedance. The input offset voltage, input offset current, and input bias current specifications apply for any supply voltage from a 5 V single supply up to a ±15 V dual supply.

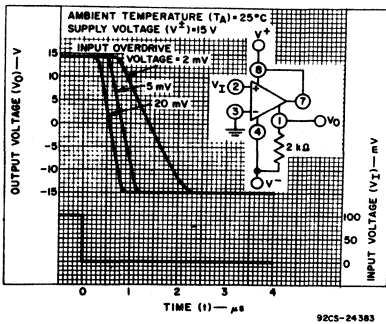


Fig. 4 - Response time for various input overdrive voltages - positive input.

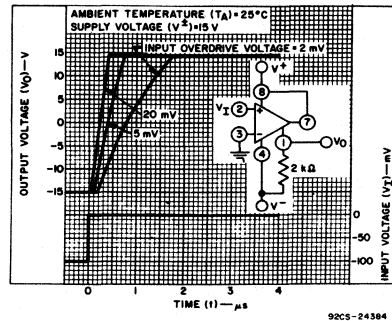


Fig. 5 - Response time for various input overdrive voltages - negative input.

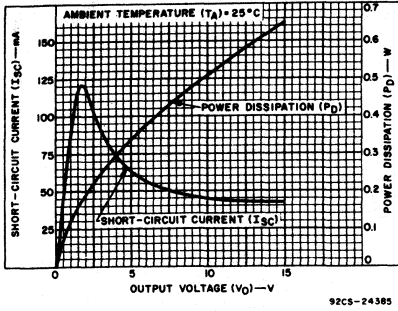


Fig. 6 - Output limiting characteristics.

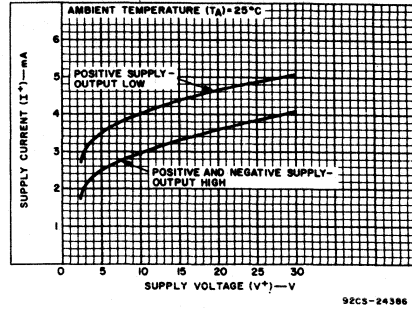


Fig. 7 - Supply current vs. supply voltage.

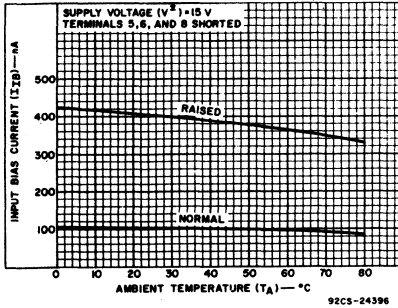


Fig. 8 - Input bias current vs. ambient temperature.

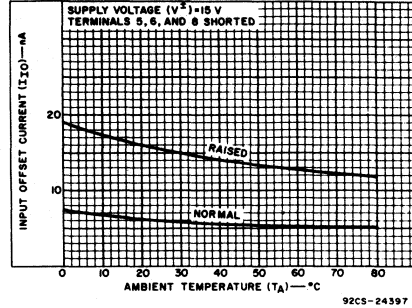


Fig. 9 - Input offset current vs. ambient temperature.

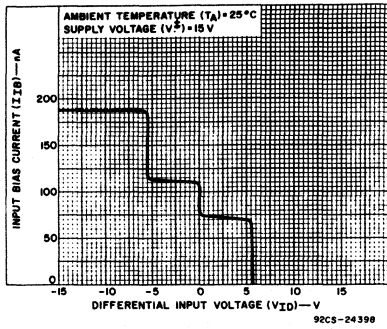


Fig. 10 - Input characteristics.

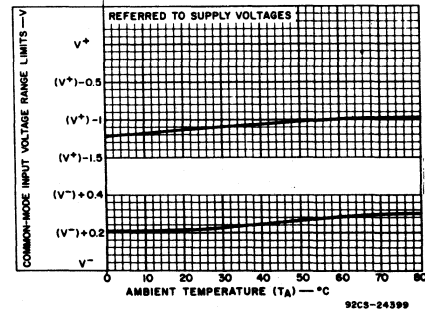


Fig. 11 - Common-mode voltage range limits vs. ambient temperature.

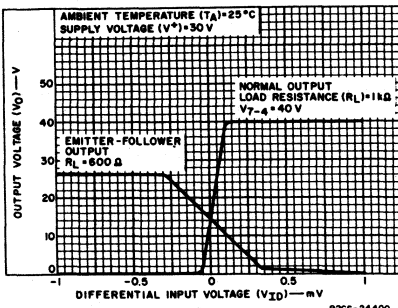


Fig. 12 - Transfer function.

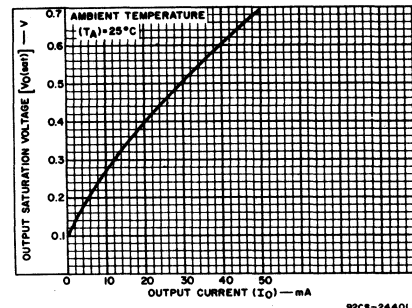


Fig. 13 - Output saturation voltage vs. output current.

Linear Integrated Circuits

CA311

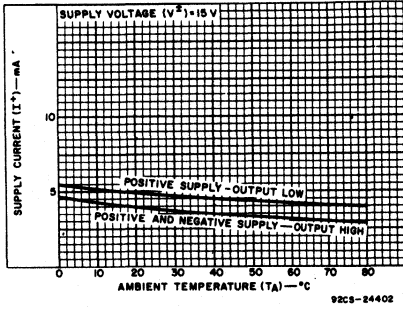


Fig. 14 - Supply current vs. ambient temperature.

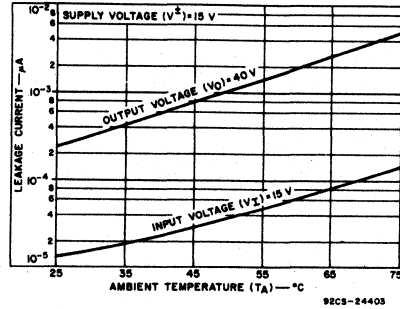


Fig. 15 - Input and output leakage current vs. ambient temperature.

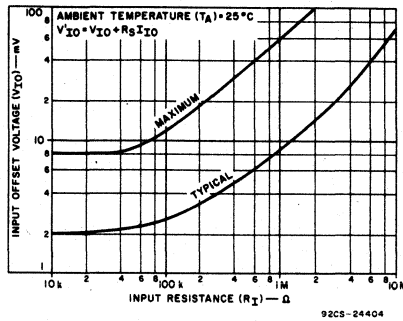


Fig. 16 - Offset error.

TYPICAL APPLICATIONS

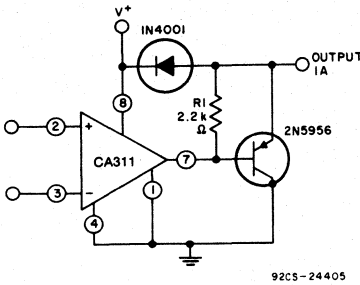


Fig. 17 - Comparator and solenoid driver.

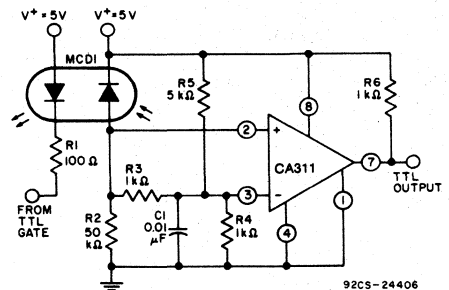
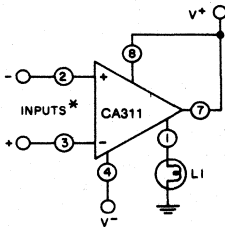


Fig. 18 - Digital transmission isolator.



*INPUT POLARITY IS REVERSED WHEN USING PIN 1 AS OUTPUT 92CS-24407

Fig. 19 - Driving a ground-referred load.

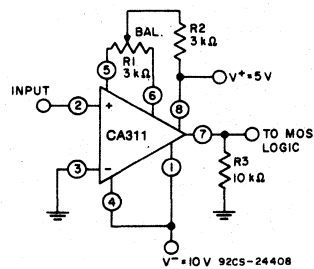


Fig. 20 - Zero-crossing detector driving MOS logic.

TYPICAL APPLICATIONS (cont'd)

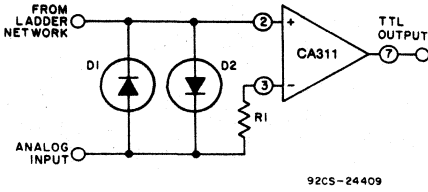


Fig. 21 - Using clamp diodes to improve response.

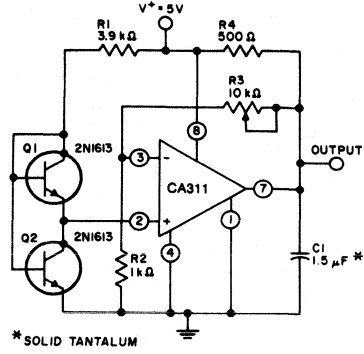


Fig. 22 - Low-voltage adjustable-reference supply.

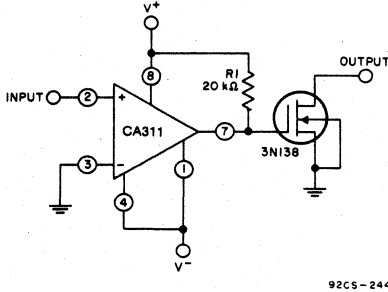
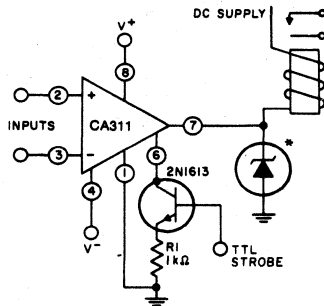
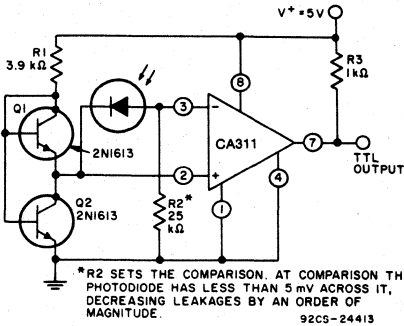


Fig. 23 - Zero-crossing detector driving and MOS switch.



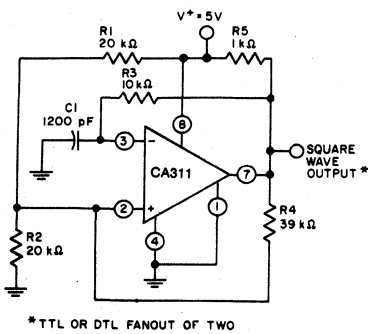
*ABSORBS INDUCTIVE KICKBACK OF RELAY AND PROTECTS IC FROM SEVERE VOLTAGE TRANSIENTS ON DC SUPPLY LINE

Fig. 24 - Relay driver with strobe.



*R2 SETS THE COMPARISON. AT COMPARISON THE PHOTODIODE HAS LESS THAN 5 mV ACROSS IT, DECREASING LEAKAGES BY AN ORDER OF MAGNITUDE.

Fig. 25 - Precision photodiode comparator.



*TTL OR DTL FANOUT OF TWO

Fig. 26 - 100-kHz free-running multivibrator.

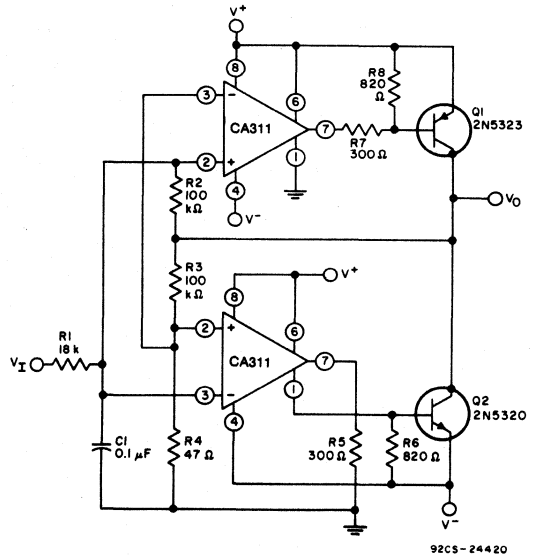
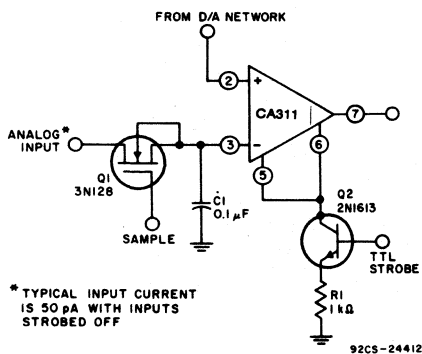


Fig. 27 - Switching power amplifier.

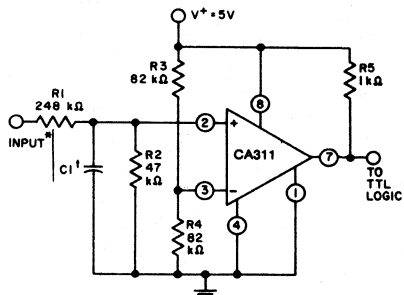
CA311

TYPICAL APPLICATIONS (cont'd)



* TYPICAL INPUT CURRENT IS 50 pA WITH INPUTS STROBED OFF

Fig. 28 - Strobing off both input and output stages.



* VALUES SHOWN ARE FOR A 0 TO 30V LOGIC SWING AND A 15V THRESHOLD.

† MAY BE ADDED TO CONTROL SPEED AND REDUCE NOISE SPIKES.

Fig. 29 - TTL interface with high-level logic.

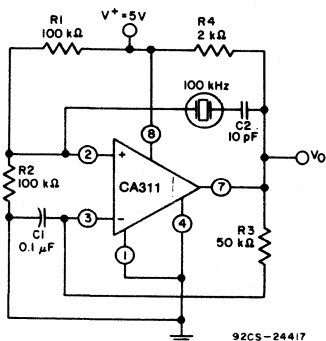
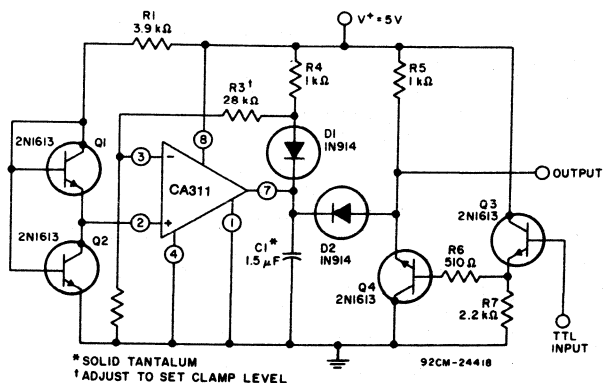


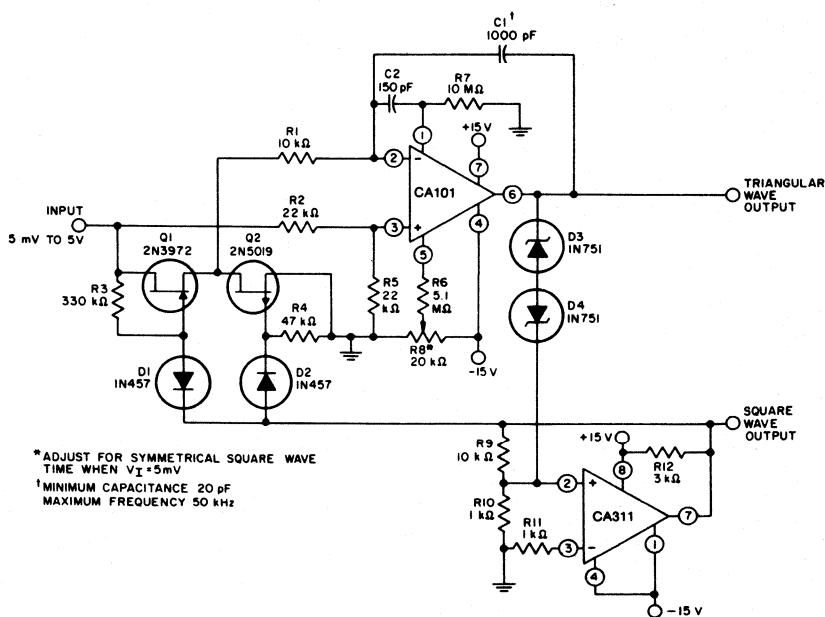
Fig. 30 - Crystal oscillator.



* SOLID TANTALUM

† ADJUST TO SET CLAMP LEVEL

Fig. 31 - Precision squarer.

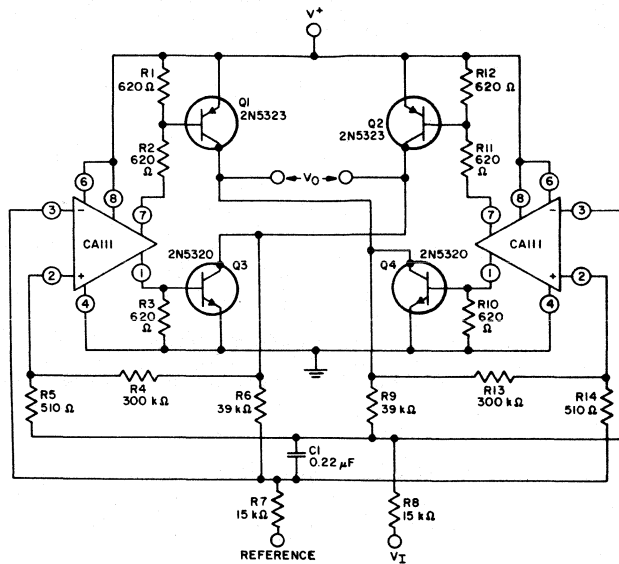


* ADJUST FOR SYMMETRICAL SQUARE WAVE TIME WHEN V_I = 5mV

† MINIMUM CAPACITANCE 20 pF
MAXIMUM FREQUENCY 50 kHz

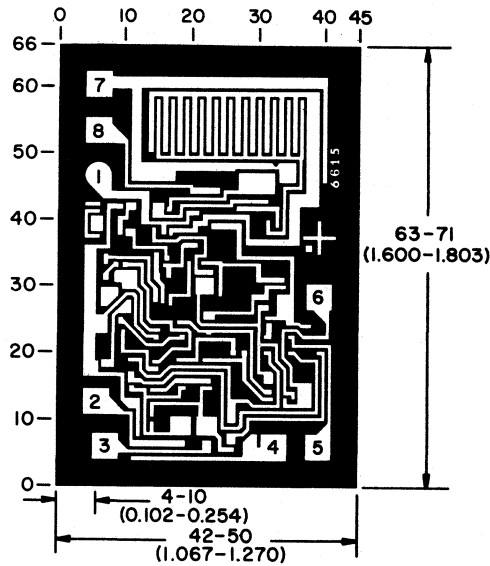
Fig. 32 - 10 Hz to 10 kHz voltage controlled oscillator.

TYPICAL APPLICATIONS (cont'd)



92CS-24421

Fig. 33 - Switching power amplifier.

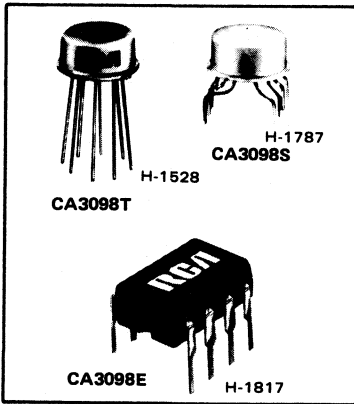


92CS-33253

Dimensions and pad layout for CA311H.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch).

CA3098



**Programmable Schmitt Trigger
— With Memory**

— Dual-Input Precision Level Detectors

Features:

- Programmable operating current
- Micropower standby dissipation
- Direct control of currents up to 150 mA
- Low input on/off current of less than 1 nA for programmable bias current of 1 μ A
- Built-in hysteresis: 20 mV max.
- Programmable hysteresis: 20 mV to V^+
- Dual reference input
- High sensor range: 100 Ω to 100 M Ω
- Stable predictable switching levels
- Temperature-compensated reference voltage

- Power can be strobed off via term. 2

Applications:

- Control of relays, heaters, LED's lamps, photo-sensitive devices, thyristors, solenoids, etc.
- Signal reconditioning
- Phase and frequency modulators
- On/off motor switching
- Schmitt triggers, level detectors
- Time delays
- Overvoltage, overcurrent, over-temperature protection
- Battery-operated equipment
- Square and triangular-wave generators

The RCA-CA3098 Programmable Schmitt Trigger is a monolithic silicon integrated circuit designed to control high-operating-current loads such as thyristors, lamps, relays, etc. The CA3098 can be operated with either a single power supply with maximum operating voltage of 16 volts, or a dual power supply with maximum operating voltage of ± 8 volts. It can directly control currents up to 150 mA and operates with microwatt standby power dissipation when the current to be controlled is less than 30 mA. The CA3098

contains the following major circuit-function features (see Fig. 1):

1. Differential amplifiers and summer: the circuit uses two differential amplifiers, one to compare the input voltage with the "high" reference, and the other to compare the input with the "low" reference. The resultant output of the differential amplifiers actuates a summer circuit which delivers a trigger that initiates a change in state of a flip-flop.

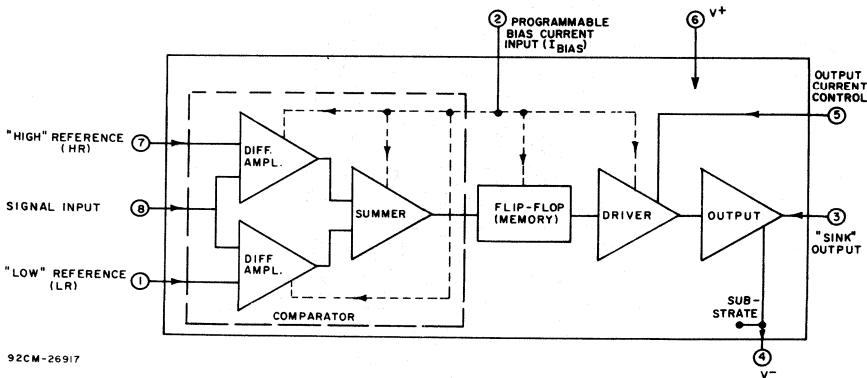


Fig. 1 — Block diagram of CA3098 programmable Schmitt trigger.

2. Flip-flop: the flip-flop functions as a bistable "memory" element that changes state in response to each trigger command.
3. Driver and output stages: these stages permit the circuit to "sink" maximum peak load currents up to 150 mA at terminal 3.
4. Programmable operating current: the circuit incorporates access at terminal 2 to permit programming the desired quiescent

operating current and performance parameters.

The CA3098 is supplied in the 8-lead dual-in-line plastic package ("Mini-Dip", E suffix), 8-lead TO-5 style package (T suffix), 8-lead TO-5-style package with formed leads "DIL-CAN" (S suffix), and in chip form (H suffix).

For information on another RCA Dual-Input Precision Level Detector, see the data bulletin for the RCA-CA3099E, File No. 620.

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$ Unless Otherwise Specified

CHARACTERISTIC	TEST CONDITIONS	Fig. No.	LIMITS			UNITS
			Min.	Typ.	Max.	
Input Offset Voltage: "Low" Ref., $V_{IO(LR)}$	$V_{LR} = \text{Gnd}, V_{HR} = 3\text{ V}$ $I_{BIAS} = 100\ \mu\text{A}$	5	-15	-3	6	mV
"High" Ref., $V_{IO(HR)}$	$V_{HR} = \text{Gnd}, V_{LR} = -3\text{ V}$ $I_{BIAS} = 100\ \mu\text{A}$	6	-10	± 10	10	
Temp. Coeff: "Low" Ref.	-55°C to $+125^\circ\text{C}$	7	-	4.5	-	$\mu\text{V}/^\circ\text{C}$
"High" Ref.	-55°C to $+125^\circ\text{C}$	8	-	± 8.2	-	
Min. Hysteresis Voltage $V_{IO(HR-LR)}$:	$V_{REG} = 6\text{ V}, V^+ = 12\text{ V}$ $I_{BIAS} = 100\ \mu\text{A}$	9	-	3	20	mV
Temp. Coeff.	-55°C to $+125^\circ\text{C}$	10	-	6.7	-	$\mu\text{V}/^\circ\text{C}$
Output Saturation Voltage, $V_{CE(SAT)}$	$V_I = 4\text{ V}, V_{REG} = 6\text{ V},$ $V^+ = 12\text{ V}, I_{BIAS} = 100\ \mu\text{A}$	11,12	-	0.72	1.2	V
Total Supply Current, I_{TOTAL} :						
"ON"	$V_I = 4\text{ V}, V_{REG} = 6\text{ V};$ $V^+ = 12\text{ V}, I_{BIAS} = 100\ \mu\text{A}$	13,14	500	710	800	μA
"OFF"	$V_I = 8\text{ V}, V_{REG} = 6\text{ V}$ $V^+ = 12\text{ V}, I_{BIAS} = 100\ \mu\text{A}$		400	560	750	μA
Input Bias Current, I_{IB} :						
$I_{B(p-n-p)}$	$V_I = 4\text{ V}, V_{REG} = 6\text{ V}$ $V^+ = 12\text{ V}, I_{BIAS} = 100\ \mu\text{A}$	15	-	42	100	nA
$I_{B(n-p-n)}$	$V_I = 8\text{ V}, V_{REG} = 6\text{ V}$ $V^+ = 12\text{ V}, I_{BIAS} = 100\ \mu\text{A}$		-	28	100	nA
Output Leakage Current, $I_{CE(OFF)}$	Current from Term. 3 when Q46 is "OFF"	-	-	-	10	μA
Switching Times:						
Delay, t_d	$I_C = 100\ \mu\text{A}$		-	600	-	ns
Fall, t_f	$I_{BIAS} = 100\ \mu\text{A}$	18	-	50	-	ns
Rise, t_r	$V^+ = 5\text{ V}$		-	500	-	ns
Storage, t_s	$V_{REG} = 2.5\text{ V}$		-	4.5	-	μs
Output Current, I_O	$V^+ = 12\text{ V}, I_{BIAS} = 50\ \mu\text{A}$	-	100	-	-	mA

Linear Integrated Circuits

CA3098

Maximum Ratings, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$:

Supply Voltage Between Terminals 6 and 4,	16	V
Output Voltage Between Terminals 7 and 4, and 3 and 4	16	V
Differential Input Voltage Between Terminals 8 and 1, and Terminals 7 and 8	10	V
Operating Voltage Range:		
Term. 8	V^- to V^+	
Term. 7	$(V^- \text{ plus } 2.0 \text{ V})$ to V^+	
Term. 1	(V^-) to $(V^+ \text{ minus } 2.0 \text{ V})$	
Load Current (Term. 3)	150	mA
Input Current to Voltage Regulator (Term. 5)	25	mA
Programmable Bias Current (Term. 2)	1	mA
Output Current Control (Term. 5)	15	mA
Power Dissipation:		
Without Heat Sink:		
Up to $T_A = 55^\circ\text{C}$		
CA3098S, CA3098T	630	mW
CA3098E	630	mW
Above $T_A = 55^\circ\text{C}$ Derate linearly at	6.67	mW/ $^\circ\text{C}$
With Heat Sink:		
Up to $T_A = 55^\circ\text{C}$		
CA3098S, CA3098T	1.6	W
Above $T_A = 55^\circ\text{C}$		
CA3098S, CA3098T Derate linearly at	16.67	mW/ $^\circ\text{C}$
Ambient Temperature Range (All Packages):		
Operating	-55 to +125	$^\circ\text{C}$
Storage	-65 to +150	$^\circ\text{C}$
Lead Temperature (During Soldering):		
At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm)		
from case for 10 seconds max.	265	$^\circ\text{C}$

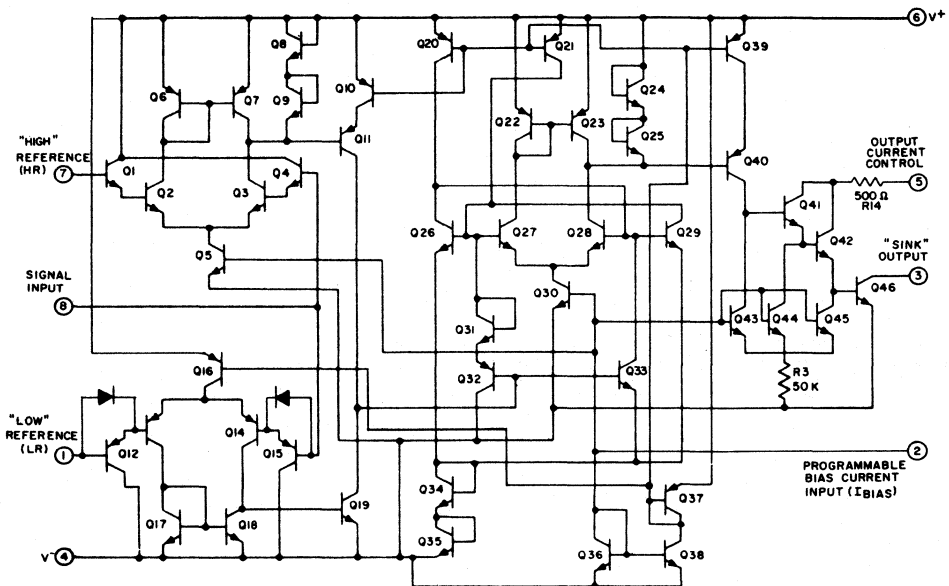


Fig. 2 - Schematic Diagram of CA3098.

92CL - 26918R1

General Description of Circuit Operation (Refer to Figs. 2, 3, 4)

When the signal-input voltage of the CA3098 is equal to or less than the "low" reference voltage (LR), current flows from an external power supply through a load connected to terminal 3 ("sink" output). This condition is maintained until the signal-input voltage rises to or exceeds the "high" reference voltage (HR), thereby effecting a change in the state of the flip-flop (memory) such that the output stage interrupts current flow in the external load. This condition, in turn, is maintained until such time as the signal again becomes equal to or less than the "low" reference voltage (VR).

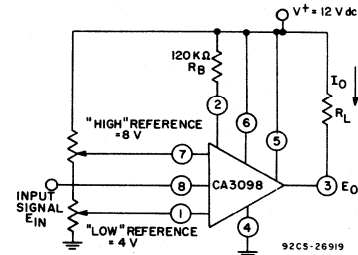


Fig. 3 — Basic hysteresis switch (Schmitt trigger).

The CA3098 comparator is unique in that it contains circuit provisions to permit programmability. This feature provides flexibility to the designer to optimize quiescent power consumption, input-circuit characteristics, hysteresis, and additionally permits independent control of the comparator, namely, pulsing, strobing, keying, squelching, etc. Programmability is accomplished by means of the bias current (I_{bias}) supplied to terminal 2.

An auxiliary means of controlling the magnitude of load-current flow at terminal 3 is provided by "sinking" current into terminal 3. Figs. 3 and 4 highlight the operation of the CA3098 when connected as a simple hysteresis switch (Schmitt trigger).

Sequence	Input Signal Level	Output Voltage (V) (Term. 3)
1	$4 \geq E_{IN} > 0$	0
2	$8 \geq E_{IN} > 4$	0
3	$E_{IN} > 8$	12
2	$8 \geq E_{IN} > 4$	12
1	$4 \geq E_{IN} > 0$	0

Fig. 4 — Resultant output states of the CA3098, shown in Fig. 3 as a function of various input signal levels.

TYPICAL CHARACTERISTIC CURVES

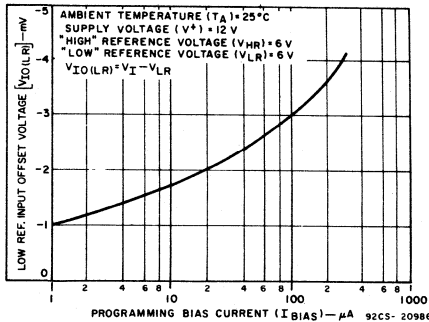


Fig. 5 — Input-offset voltage ("low" reference) vs. programming bias current.

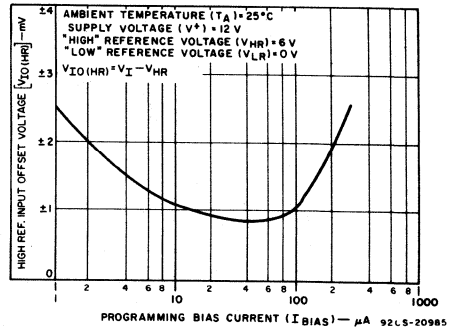


Fig. 6 — Input-offset voltage ("high" reference) vs. programming bias current.

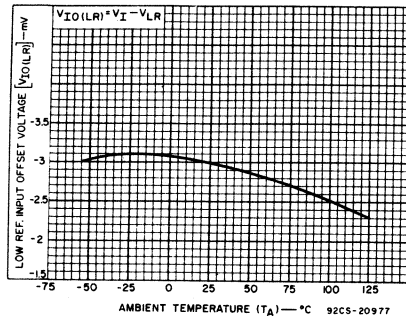


Fig. 7 — Input-offset voltage ("low reference) vs. ambient temperature.

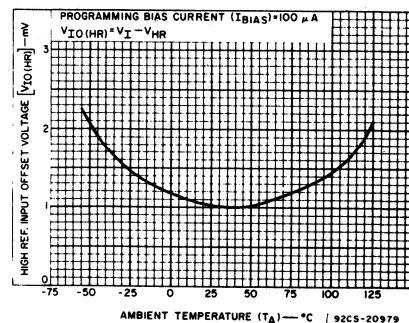


Fig. 8 — Input-offset voltage ("high reference) vs. ambient temperature.

TYPICAL CHARACTERISTIC CURVES (Cont'd)

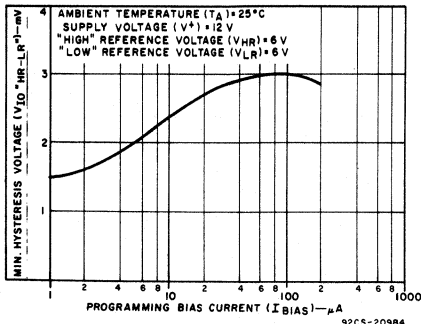


Fig. 9 - Min. hysteresis voltage vs. programming bias current.

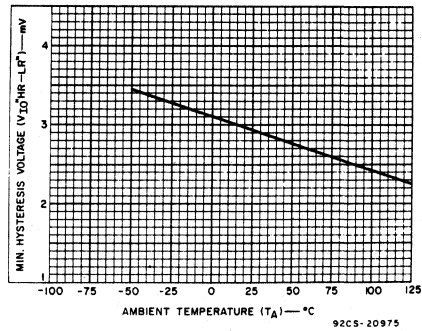


Fig. 10 - Min. hysteresis voltage vs. ambient temperature.

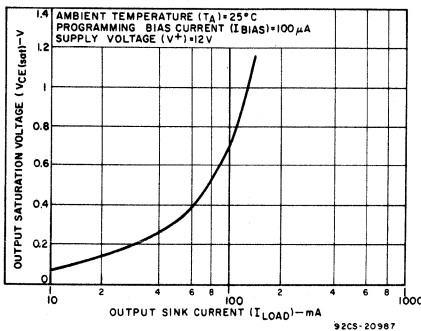


Fig. 11 - Output saturation voltage vs. output sink current.

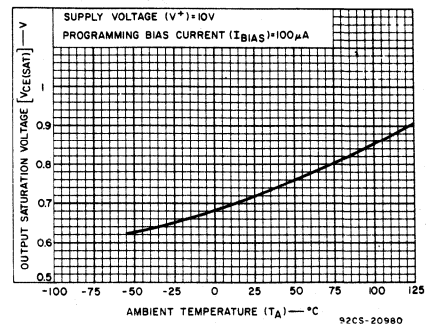


Fig. 12 - Output saturation voltage vs. ambient temperature.

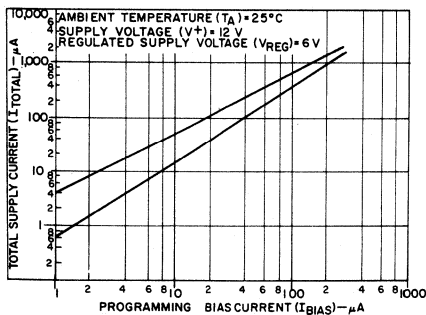


Fig. 13 - Total supply current vs. programming bias current.

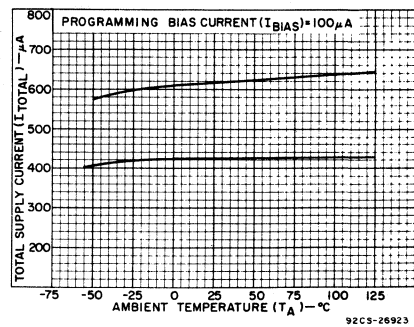


Fig. 14 - Total supply current vs. ambient temperature.

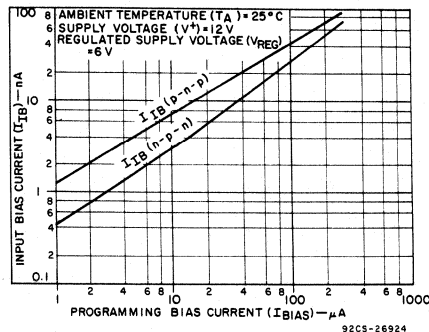


Fig. 15 - Input bias current vs. programming bias current.

TEST CIRCUIT

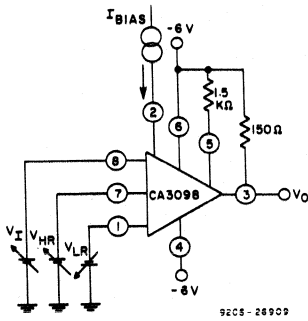
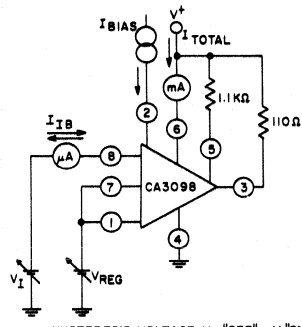


Fig. 16 - Input-offset voltage test circuit.



HYSTERESIS VOLTAGE = V_I "OFF" - V_I "ON"
Fig. 17 - Min. hysteresis voltage, total supply current, and input-bias-current test circuit.

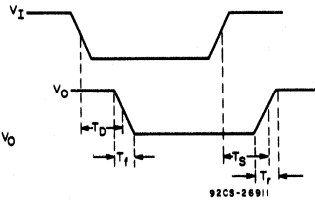
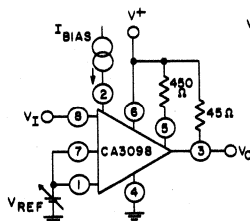


Fig. 18 - Switching time test circuit.

TYPICAL APPLICATIONS

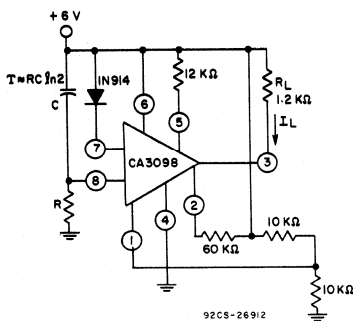


Fig. 19 - Time delay circuit: Terminal 3 "sinks" after τ seconds.

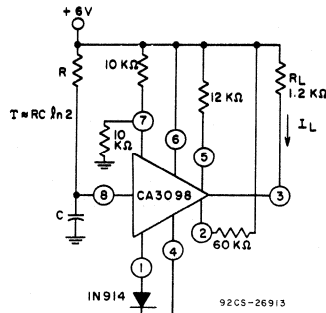


Fig. 20 - Time delay circuit: "sink" current interrupted after τ seconds.

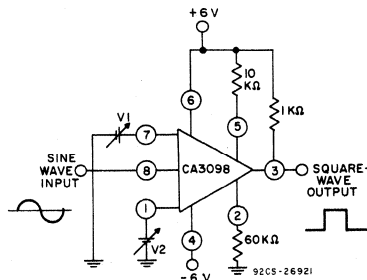
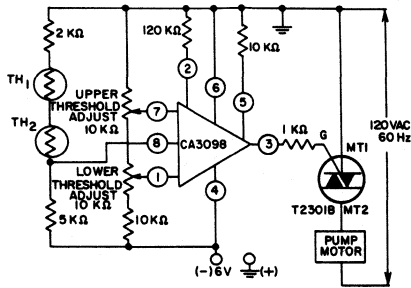


Fig. 21 - Sine-wave to square-wave converter with duty-cycle adjustment (V_1 and V_2).

Linear Integrated Circuits

CA3098

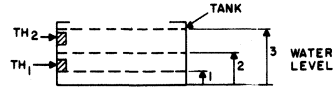
TYPICAL APPLICATIONS (Cont'd)



92CS-26920

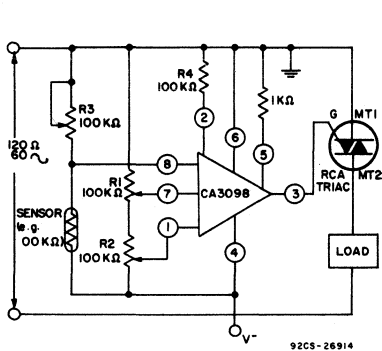
- Notes**
- (a) Motor pump is "ON" when water level rises above thermistor TH₂.
 - (b) Motor pump remains "ON" until water level falls below thermistor TH₁.
 - (c) Thermistors, operate in self-heating mode.

Fig. 22(a) - Water-level control.



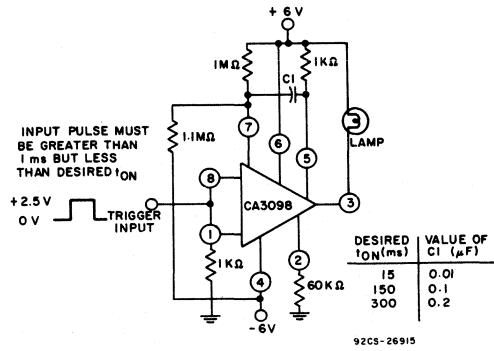
92CS-26787

Fig. 22(b) - Water level diagram for circuit of Fig. 22(a).



92CS-26914

Fig. 23 - OFF/ON control of triac with programmable hysteresis.



92CS-26915

Fig. 24 - One-shot multivibrator.

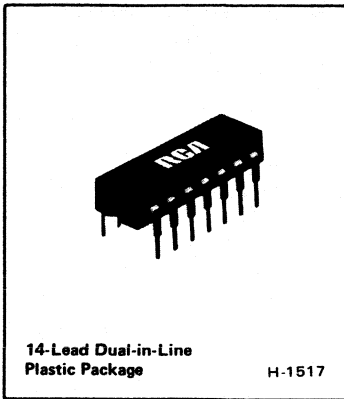
Programmable Comparator - - With Memory

Features:

- Programmable operating current
- Micro-power standby dissipation
- Directly controls current up to 150 mA
- Low input on/off current of less than 1 nA for programmable bias current of 1 μ A
- Built-in hysteresis: 10 mV max.
- Programmable hysteresis: 10 mV to V^+
- Dual reference input
- High sensor range: 100 Ω to 100 M Ω
- Stable predictable switching levels
- Temperature-compensated reference voltage

Applications:

- Control of relays, heaters, LED's, lamps, photo-sensitive devices, thyristors, solenoids, etc.
- Signal reconditioning
- Phase and frequency modulators
- On/off motor switching
- Schmitt triggers, level detectors
- Time delays
- Overvoltage, overcurrent, overtemperature protection
- Battery-operated equipment
- Square and triangular-wave generators



14-Lead Dual-in-Line
Plastic Package

H-1517

RCA-CA3099E* Programmable Comparator is a monolithic silicon integrated circuit designed to control high-operating-current loads such as thyristors, lamps, relays, etc. The CA3099E can be operated with either a single power supply with maximum operating voltage of 16 volts, or a dual power supply with a maximum operating voltage of ± 8 volts. It can directly control currents up to 150 mA. It operates with microwatt standby power dissipation when the current to be

* Formerly Developmental No. TA6189.

controlled is less than 30 mA. The CA3099E contains the following six (6) major circuit-function features (Figure 1):

1. **Differential amplifiers and summer;** the circuit uses two differential amplifiers, one to compare the input voltage with the "high" reference, and the other to compare the input with the "low" reference. The resultant output of the differential amplifiers actuates a summer circuit which delivers a trigger that initiates a change in state of a flip-flop.

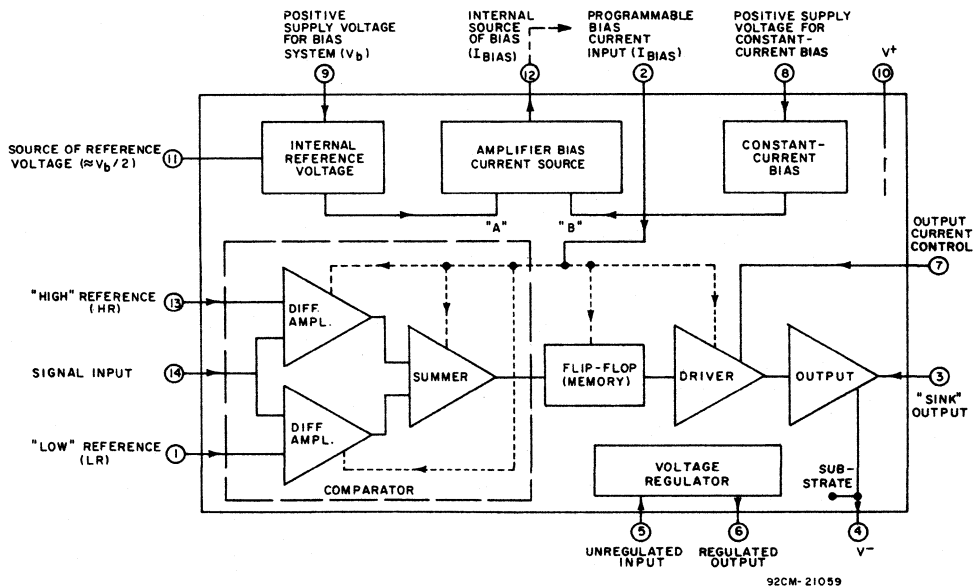


Fig. 1—Block diagram of CA3099E programmable comparator.
(See page 3 for general description of circuit operation.)

Linear Integrated Circuits

CA3099E

Major Circuit-Function Features (Cont'd)

- Flip-flop;** the flip-flop functions as a bistable "memory" element that changes state in response to each trigger command.
- Driver and output stages;** these stages permit the circuit to "sink" maximum peak load currents up to 150 mA at terminal 3.
- Programmable operating current;** the circuit incorporates a separate terminal to permit programming the desired quiescent operating current and performance parameters.
- Internal sources of reference voltage and programmable bias current;** an integral circuit supplies a temperature-compensated reference voltage ($V_b/2$) which is about 1/2 of the externally applied bias voltage (V_b). Additionally, integral circuitry can optionally be used to supply an uncompensated constant-current source of bias (I_{bias}).
- Voltage regulator;** provides optional on-chip voltage regulation when power for the CA3099E is provided by an unregulated supply.

Maximum Ratings, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$:

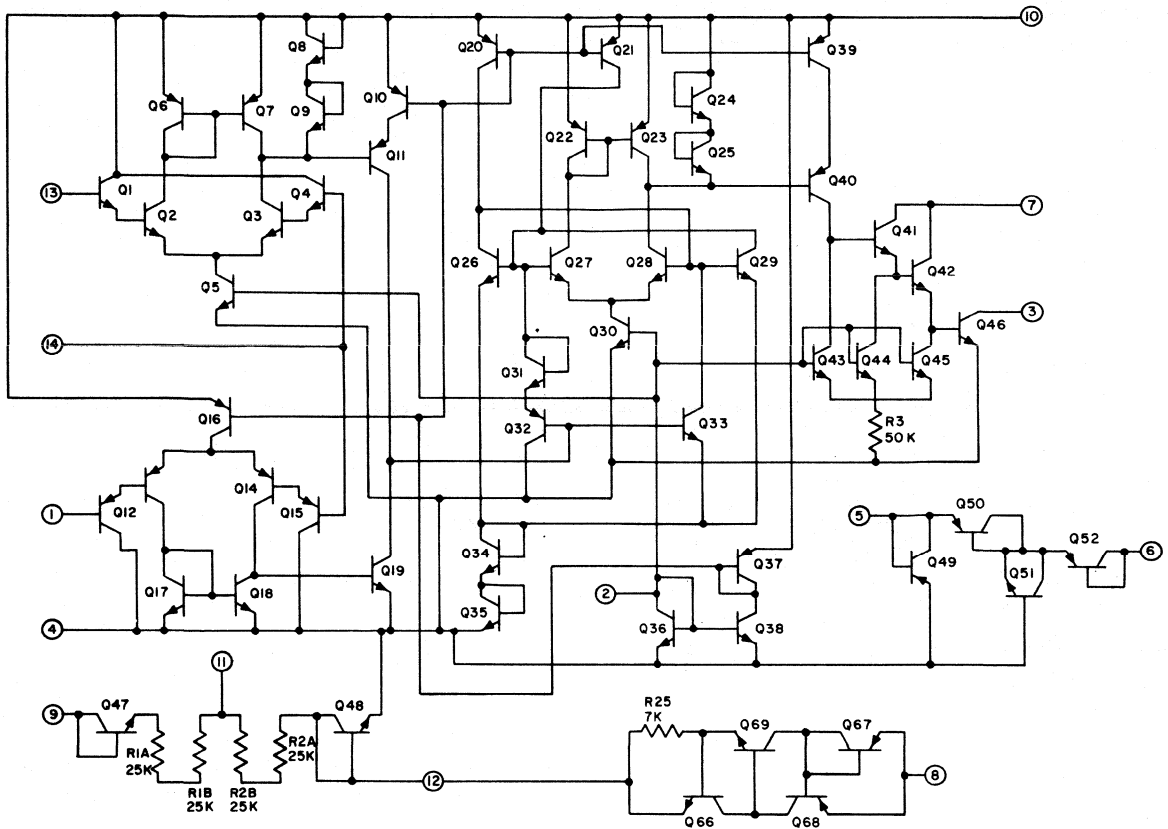
Supply Voltage Between Terminals 10 and 4, 9 and 4, 8 and 4	16	V
Output Voltage Between Terminals 7 and 4, and 3 and 4	16	V
Differential Input Voltage Between Terminals 14 and 1, and Terminals 13 and 14	10	V
Operating Voltage Range:		
Term. 14	0 V to V^+	
Term. 13	2.0 V to V^+	
Term. 1	0 V to V^+ minus 2.0 V	
Load Current (Term. 3)	150	mA
Input Current to Voltage Regulator (Term. 5)	25	mA
Programming Bias Current (Term. 2)	1	mA
Output Current Control (Term. 7)	15	mA
Power Dissipation:		
Up to $T_A = 55^\circ\text{C}$	750	mW
Above $T_A = 55^\circ\text{C}$	Derate Linearly at	6.67 mW/ $^\circ\text{C}$
Ambient Temperature Range:		
Operating	-55 to +125	$^\circ\text{C}$
Storage	-65 to +150	$^\circ\text{C}$
Lead Temperature (During Soldering):		
At distance not less than 1/32 inch (3.17 mm) from seating plane for 10 s maximum	+265	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS AT $T_A = 25^\circ\text{C}$ (Unless otherwise indicated)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS $T_A = 25^\circ\text{C}$ Unless Otherwise Indicated	FIG. No.	LIMITS			UNIT
				MIN.	TYP.	MAX.	
Reference Voltage	V_{REF}	Term. 9 = 12 V, Term. 4 = Grd, Term. 11 = Test	—	5.7	6	6.3	V
Reference Voltage Temperature Coefficient			—	—	100	—	$\mu\text{V}/^\circ\text{C}$
Regulated Supply Voltage	V_{REG}	Term. 5 1K to 12V, Term. 4 = Grd, Term. 6 10K to Grd	5	6	7.2	8	V
Regulated Supply Voltage Temperature Coefficient			5	—	2.9	—	$\text{mV}/^\circ\text{C}$
Input Offset Voltage: "Low" Reference	$V_{IO}(\text{LR})$	$V_{LR} = \text{Grd}$, $V_{HR} = 3 \text{ V}$, $I_{BIAS} = 100 \mu\text{A}$	20, 6	-8	-3	2	mV
"High" Reference	$V_{IO}(\text{HR})$	$V_{HR} = \text{Grd}$, $V_{LR} = -3 \text{ V}$, $I_{BIAS} = 100 \mu\text{A}$	20, 7	-5	± 1	5	
"Low" Reference Temp. Coefficient		-55 $^\circ\text{C}$ to +125 $^\circ\text{C}$	20, 8	—	4.5	20	$\mu\text{V}/^\circ\text{C}$
"High" Reference Temp. Coefficient		-55 $^\circ\text{C}$ to +125 $^\circ\text{C}$	20, 9	—	± 8.2	± 20	
Min. Hysteresis Voltage	$V_{IO}(\text{HR}-\text{LR})$	$V_{REG} = 6 \text{ V}$, $V^+ = 12 \text{ V}$, $I_{BIAS} = 100 \mu\text{A}$	21, 10	—	3	10	mV
Min. Hysteresis Voltage Temperature Coefficient		-55 $^\circ\text{C}$ to +125 $^\circ\text{C}$	11	—	6.7	20	$\mu\text{V}/^\circ\text{C}$
Output Saturation Voltage	$V_{CE}(\text{SAT})$	$V_I = 4 \text{ V}$, $V_{REG} = 6 \text{ V}$, $V^+ = 12 \text{ V}$, $I_{BIAS} = 100 \mu\text{A}$	21, 12, 13	—	0.72	1.2	V
Total Supply Current: I _{TOTAL} "ON"	I_{TOTAL}	$V_I = 4 \text{ V}$, $V_{REG} = 6 \text{ V}$, $V^+ = 12 \text{ V}$, $I_{BIAS} = 100 \mu\text{A}$	21, 14, 15	600	710	800	μA
I _{TOTAL} "OFF"		$V_I = 8 \text{ V}$, $V_{REG} = 6 \text{ V}$, $V^+ = 12 \text{ V}$, $I_{BIAS} = 100 \mu\text{A}$	21, 14, 15	420	560	750	
Input Bias Current: $I_{B(p-n-p)}$	I_{IB}	$V_I = 4 \text{ V}$, $V_{REG} = 6 \text{ V}$, $V^+ = 12 \text{ V}$, $I_{BIAS} = 100 \mu\text{A}$	21, 16, 17	—	33	200	nA
$I_{B(n-p-n)}$		$V_I = 8 \text{ V}$, $V_{REG} = 6 \text{ V}$, $V^+ = 12 \text{ V}$, $I_{BIAS} = 100 \mu\text{A}$	21, 16, 17	—	20	60	
Output Leakage Current	$I_{CE}(\text{OFF})$	Current from Term. 3 when Q46 is "OFF"	—	—	—	10	μA
Internal Bias Current	I_{IBC}		18, 19	120	200	280	μA
Switching Times:							
Delay	t_d	$I_C = 100 \mu\text{A}$ $I_{BIAS} = 100 \mu\text{A}$ $V^+ = 5 \text{ V}$ $V_{REG} = 2.5 \text{ V}$	22	—	600	—	ns
Fall	t_f		22	—	50	—	
Rise	t_r		22	—	500	—	
Storage	t_s		22	—	4.5	—	

Voltage Comparators

CA3099E



92CM-20997

Fig.2—Schematic diagram of CA3099E.

General Description of Circuit Operation (Refer to Fig.1)

When the signal-input voltage of the CA3099E is equal to or less than the "low" reference voltage (LR), current flows from an external power supply through a load connected to terminal 3 ("sink" output). This condition is maintained until the signal-input voltage rises to or exceeds the "high" reference voltage (HR), thereby effecting a change in the state of the flip-flop (memory) such that the output stage interrupts current flow in the external load. This condition, in turn, is maintained until such time as the signal again becomes equal to or less than the "low" reference voltage (VR).

The CA3099E comparator is unique in that it contains circuit provisions to permit programmability. This feature provides flexibility to the designer to optimize quiescent power consumption, input-circuit characteristics, hysteresis, and additionally permits independent control of the comparator, namely, pulsing, strobing, keying, squelching, etc. Programmability is accomplished by means of the bias current (I_{bias}) supplied to terminal 2. As an alternative to externally supplied bias current, the CA3099E contains an internal

source of regulated bias current accessible at terminal 12. This internal source of bias current is developed by two alternative methods; in the first method, bias voltage (V_B) applied at terminal 9 develops a source of temperature-compensated reference voltage ($\approx V_B/2$) at terminal 11 and additionally supplies a source of bias current at terminal 12 via line "A". Alternately, when a positive supply voltage is applied at terminal 8, a source of constant-current biasing is provided at terminal 12 via line "B".

An auxiliary means of controlling the magnitude of load-current flow at terminal 3 is provided by "sinking" current into terminal 7. The CA3099E contains an on-chip voltage regulator which may optionally be used to regulate the voltages and bias currents (exclusive of the load current at terminal 3) needed for the operation of the IC.

Fig. 2 is the schematic diagram of the CA3099E. Figs. 3 and 4 are, respectively, functional and logic diagrams of CA3099E operation.

CA3099E

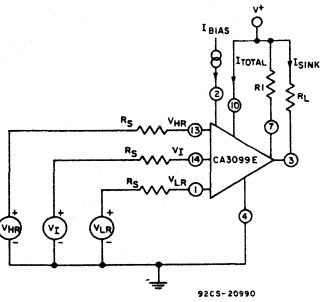


Fig. 3—Functional diagram.

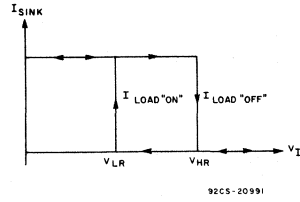


Fig. 4—Logic diagram.

TYPICAL CHARACTERISTIC CURVES

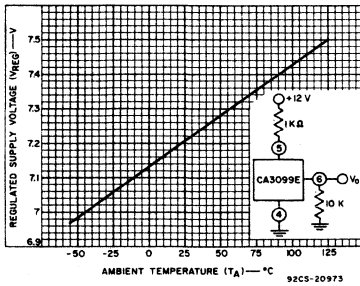


Fig. 5—Regulated supply voltage vs. ambient temperature.

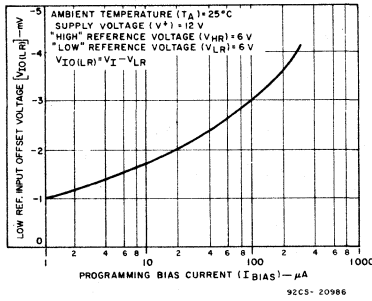


Fig. 6—Input-offset voltage ("low" reference) vs. programming bias current.

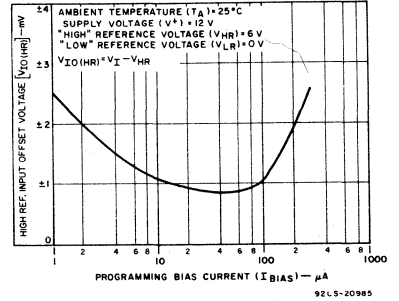


Fig. 7—Input-offset voltage ("high" reference) vs. programming bias current.

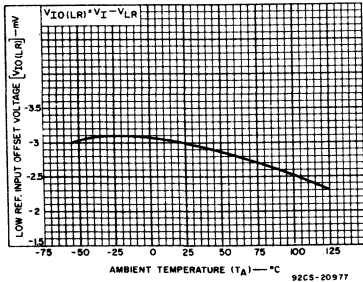


Fig. 8—Input-offset voltage ("low" reference) vs. ambient temperature.

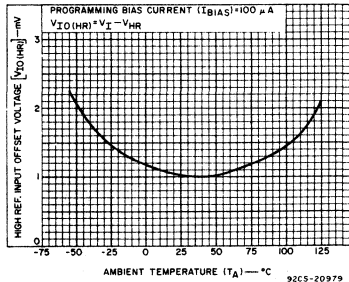


Fig. 9—Input-offset voltage ("high" reference) vs. ambient temperature.

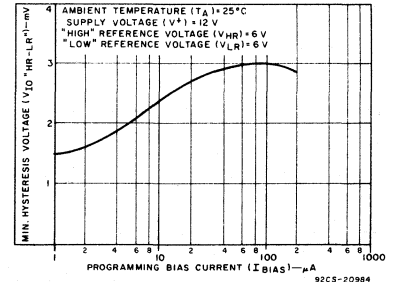


Fig. 10—Min. hysteresis voltage vs. programming bias current.

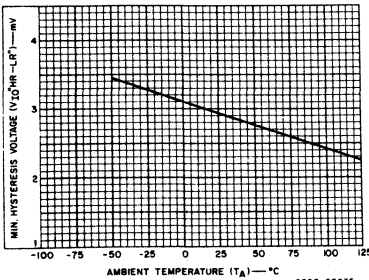


Fig. 11—Min. hysteresis voltage vs. ambient temperature.

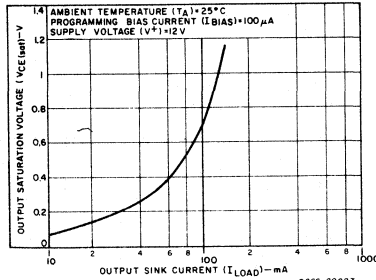


Fig. 12—Output saturation voltage vs. output sink current.

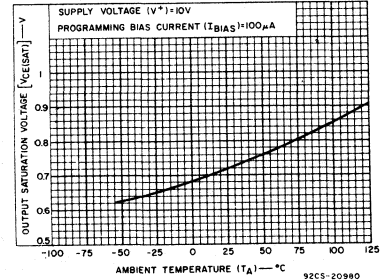


Fig. 13—Output saturation voltage vs. ambient temperature.

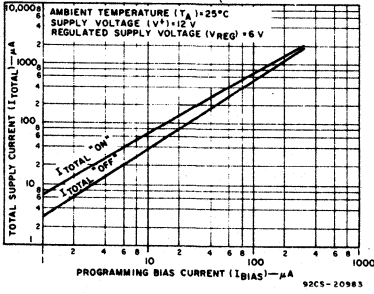


Fig. 14—Total supply current vs. programming bias current.

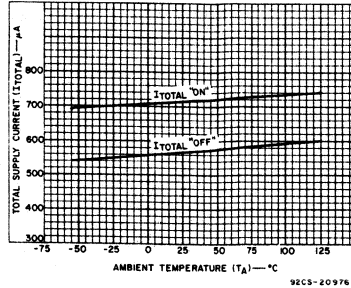


Fig. 15—Total supply current vs. ambient temperature.

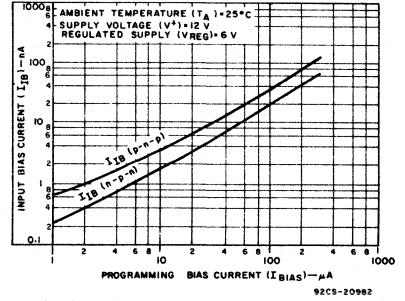


Fig. 16—Input bias current vs. programming bias current.

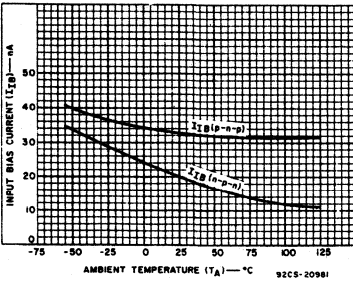


Fig. 17—Input bias current vs. ambient temperature.

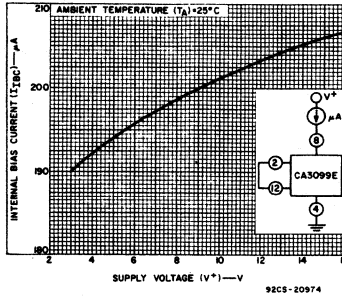


Fig. 18—Internal bias current vs. supply voltage.

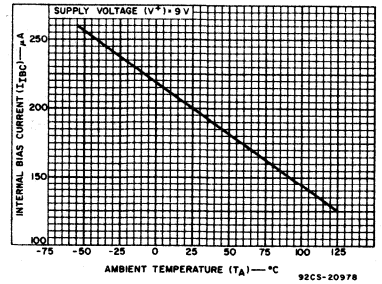


Fig. 19—Internal bias current vs. ambient temperature.

TEST CIRCUITS

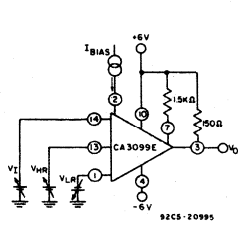


Fig. 20—Input-offset voltage test circuit.

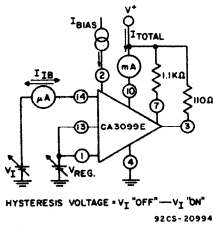


Fig. 21—Min. hysteresis voltage, total supply current, and input-bias-current test circuit.

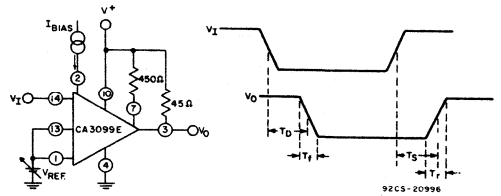


Fig. 22—Switching time test circuit.

TYPICAL APPLICATIONS

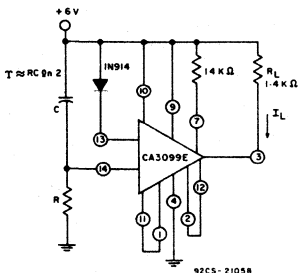


Fig. 23(a)—Time delay circuit: Terminal 3 "sinks" after T seconds.

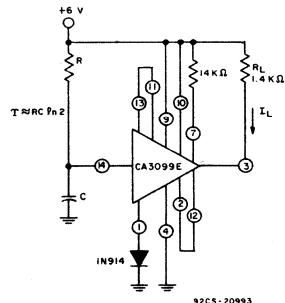


Fig. 23(b)—Time delay circuit: "sink" current interrupted after T seconds.

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CA3099E

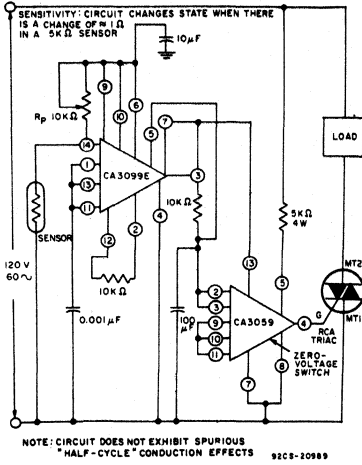


Fig.24—Sensitive temperature control.

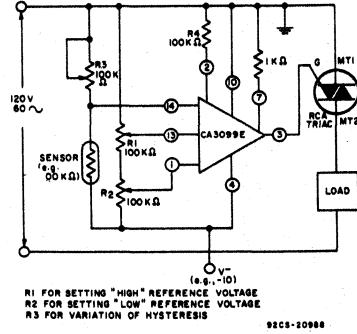


Fig.25—OFF/ON control of triac with programmable hysteresis.

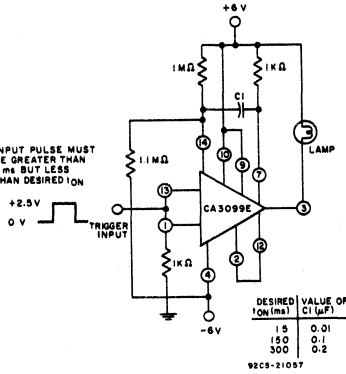


Fig.26—One-shot multivibrator.

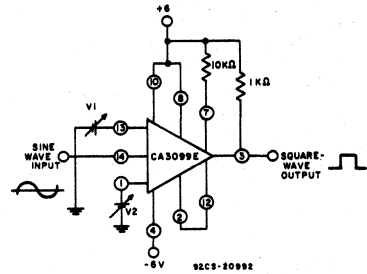
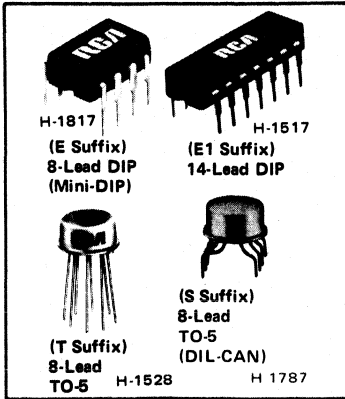


Fig.27—Sine-wave to square-wave converter with duty-cycle adjustment (V_1 and V_2).

BiMOS Dual Voltage Comparators

With MOS/FET Input, Bipolar Output



Features:

- MOS/FET input stage:
 - (a) Very high input impedance (Z_{IN}) - 1.7 T Ω typ.
 - (b) Very low input current - 3.5 pA typ. at +5 V supply voltage
 - (c) Low input-offset voltage (V_{IO}) - to 6 mV max. (CA3290B)
 - (d) Wide common-mode input-voltage range (V_{ICM}) - can be swung 1.5 V (typ.) below negative supply-voltage rail
 - (e) No phase reversal of output signal for input signals down to 5 V below negative supply-voltage rail
 - (f) MOS/FET input stage - zener diode protected
 - (g) Virtually eliminates errors due to flow of input currents
- Wide supply-voltage range:
 - Single supply - 4 to 36 V dc
 - Dual supply - $+3.5$ to ± 18 V dc
 - (B-types up to 44 or ± 22 V dc)

- Very low supply-current drain - 0.8 mA at +5 V
- Differential input-voltage range - up to ± 36 V
- Low output saturation voltage - 120 mV at 4 mA
- Output voltage compatible with TTL, DTL, ECL, MOS, and CMOS logic systems
- All types are rated for operation over the range of -55 to $+125^\circ\text{C}$
- Stable V_{IO} vs. time due to source-follower inputs

Applications:

- High-source-impedance voltage comparators
- Long time delay circuits
- Square-wave generators
- A/D converters
- Window comparators

SELECTION CHART

Selection	Characteristic				Package & Suffix			
	Max. V_{IO} (mV)	Max. I_I (pA)	Min. A_{OL}	V^+ (V)	TO-5		Plastic	
					Std.	DIL-CAN	8-Ld.	14-Ld.
CA3290B	6	30	50K	44	T	S	—	—
CA3290A	10	40	25K	36	T	S	E	E1
CA3290	20	50	25K	36	T	S	E	E1

The CA3290 is also available in chip form (H suffix)

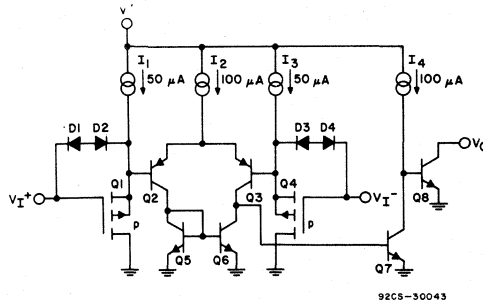


Fig. 1 → Basic CA3290 comparator.

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CA3290, CA3290A, CA3290B

MAXIMUM RATINGS, *Absolute-Maximum Values:*

DC SUPPLY VOLTAGE:

Single Supply:

CA3290B	+44 V
CA3290A, CA3290	+36 V

Dual Supply:

CA3290B	± 22 V
CA3290A, CA3290	± 18 V

DIFFERENTIAL INPUT VOLTAGE ± 36 V or ± [(V⁺-V⁻)+5 V]
(whichever is less)

COMMON-MODE INPUT VOLTAGE V⁺+5 V to V⁻-5 V

DEVICE DISSIPATION:

Up to 55°C	630 mW
Above 55°C	Derate linearly at 6.67 mW/°C

OUTPUT-TO-V⁻ SHORT CIRCUIT DURATION* CONTINUOUS

TEMPERATURE RANGE, ALL TYPES:

Operating	-55 to +125°C
Storage	-65 to +150°C

INPUT TERMINAL CURRENT

..... 1 mA

LEAD TEMPERATURE (DURING SOLDERING):

AT DISTANCE 1/16 ± 1/32 INCH (1.59 ± 0.79 MM) 265°C

FROM CASE FOR 10 SECONDS MAX.

*Short circuits from the output to V⁺ can cause excessive heating and eventual destruction of the device.

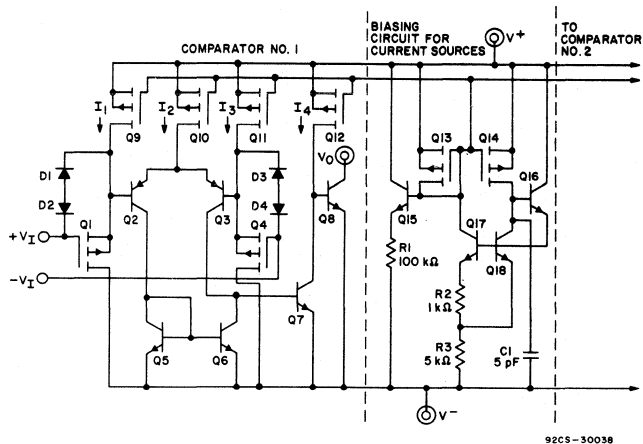


Fig. 2 — Schematic diagram of CA3290 (only one is shown).

CIRCUIT DESCRIPTION

The Basic Comparator

Fig. 1 shows the basic circuit diagram for one of the two comparators in the CA3290. It is generically similar to the industry-type "139" comparators, with PMOS transistors replacing p-n-p transistors as input stage elements. Transistors Q1 through Q4 comprise the differential input stage, with Q5 and Q6 serving as a mirror-connected active load and differential-to-single-ended converter. The differential input at Q1 and Q4 is amplified so as to toggle Q6 in accordance with the input-signal polarity. For example, if +V_{I(N)} is greater than -V_{I(N)}, Q1, Q2, and current mirror transistors Q5 and Q6 will be turned off; transistors Q3, Q4, and Q7 will

be turned on, causing Q8 to be turned off. The output is pulled positive when a load resistor is connected between the output and V⁺.

In essence, Q1 and Q4 function as source-followers to drive Q2 and Q3, respectively, with zener diodes D1 through D4 providing gate-oxide protection against input voltage transients (e.g., static electricity). The current flow in Q1 and Q2 is established at approximately 50 microamperes by constant-current sources I₁ and I₃, respectively. Since Q1 and Q4 are operated with a constant current load, their gate-to-source voltage drops will be effectively constant as long as the input voltages are within the common-mode

CA3290, CA3290A, CA3290B

range. As a result, the input offset voltage ($V_{GS}(Q1) + V_{BE}(Q2) - V_{BE}(Q3) - V_{GS}(Q4)$) will not be degraded when a large differential dc voltage is applied to the device for extended periods of time at high temperatures.

Additional voltage gain following the first stage is provided by transistors Q7 and Q8. The collector of Q8 is open, offering the user a wide variety of options in applications. An additional discrete transistor can be added if it becomes necessary to boost the output sink-current capability.

The detailed schematic diagram for one com-

parator and the common current-source biasing is shown in Fig. 2. PMOS transistors Q9 through Q12 are the current-source elements identified in Fig. 1 as I1 through I4, respectively. Their gate-source potentials (V_{GS}) are supplied by a common bus from the biasing circuit shown in the right-hand portion of the Fig. 2. The currents supplied by Q10 and Q12 are twice those supplied by Q9 and Q11. The transistor geometries are appropriately scaled to provide the requisite currents with common V_{GS} applied to Q9 through Q12.

ELECTRICAL CHARACTERISTICS at $T_A = -55$ to $+125^\circ\text{C}$

CHARACTERISTIC	TEST CONDITIONS		VALUES						UNITS
			CA3290B		CA3290A		CA3290		
	V ⁺	Typ.	Max.	Typ.	Max.	Typ.	Max.		
Input Offset Voltage, V_{IO}	$V_{CM}=1.4\text{ V}$, $V_O=1.4\text{ V}$	5 V	3.5	—	4.5	—	8.5	—	mV
	$V_{CM}=0\text{ V}$, $V_O=0\text{ V}$	$\pm 15\text{ V}$	3.5	—	8.5	—	8.5	—	
Temp. Coefficient of Input Offset Voltage, $\Delta V_{IO}/\Delta T$			8	—	8	—	8	—	$\mu\text{V}/^\circ\text{C}$
Input Offset Current, I_{IO}	$V_{CM}=1.4\text{ V}$	5 V	2	22	2	28	2	32	nA
	$V_{CM}=0\text{ V}$	$\pm 15\text{ V}$	7	22	7	28	7	32	
Input Current, I_I^Δ	$V_{CM}=1.4\text{ V}$	5 V	2.8	32	2.8	45	2.8	55	nA
	$V_{CM}=0\text{ V}$	$\pm 15\text{ V}$	13	32	13	45	13	55	
Supply Current, I^{+*}	$R_L = \infty$	5 V	0.85	1.6	0.85	1	0.85	1.6	mA
		30 V	1.62	3.5	1.62	3	1.62	3.5	
Voltage Gain, A_{OL}	$R_L = 15\text{ k}\Omega$	$\pm 15\text{ V}$	150	—	150	—	150	—	V/mV
			103	—	103	—	103	—	dB
Saturation Voltage $I_{SINK} = 4\text{ mA}$	$V^+=5\text{ V}$, $+V_I=0\text{ V}$, $-V_I=1\text{ V}$	$+125^\circ\text{C}$	0.22	0.7	0.22	0.7	0.22	0.7	V
		-55°C	0.1	—	0.1	—	0.1	—	
Output Leakage Current, I_{OL}		15 V	65	—	65	—	65	—	nA
		36 V	130	1k	130	1k	130	1k	

Δ At $T_A = +125^\circ\text{C}$

* At $T_A = -55^\circ\text{C}$

Linear Integrated Circuits

CA3290, CA3290A, CA3290B

ELECTRICAL CHARACTERISTICS AT $T_A = 25^\circ\text{C}$

CHARACTERISTIC	TEST COND. V^+	LIMITS						UNITS
		CA3290B			CA3290A			
		Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage, V_{IO} $V_{CM}=1.4\text{ V}$ $V_O=1.4\text{ V}$	5 V	–	3	6	–	4	10	mV
	$V_{CM}=0\text{ V}$ $V_O=0\text{ V}$	$\pm 15\text{ V}$	–	3	6	–	4	
Input Current, I_I $V_{CM}=1.4\text{ V}$	5 V	–	3.5	30	–	3.5	40	pA
	$V_{CM}=0\text{ V}$	$\pm 15\text{ V}$	–	12	30	–	12	
Input Offset Current, I_{IO} $V_{CM}=1.4\text{ V}$	5 V	–	2	20	–	2	25	pA
	$V_{CM}=0\text{ V}$	$\pm 15\text{ V}$	–	7	20	–	7	
Common-Mode Input-Voltage Range, V_{ICR} $V_O=1.4\text{ V}$	5 V	$V^+-3.5$ V^-	$V^+-3.1$ $V^- -1.5$	–	$V^+-3.5$ V^-	$V^+-3.1$ $V^- -1.5$	–	V
	$V_O=0\text{ V}$	$\pm 15\text{ V}$	$V^+-3.8$ V^-	$V^+-3.4$ $V^- -1.6$	–	$V^+-3.8$ V^-	$V^+-3.4$ $V^- -1.6$	
Supply Current, I^+ $R_L = \infty$	30 V	–	1.35	3	–	1.35	3	mA
	5 V	–	0.8	1.4	–	0.8	1.4	
Voltage Gain, A_{OL} $R_L=15\text{ k}\Omega$	$\pm 15\text{ V}$	50	800	–	25	800	–	V/mV
		94	118	–	88	118	–	dB
Output Sink Current $V_O=1.4\text{ V}$	5 V	6	30	–	6	30	–	mA
Saturation Voltage $+V_I=0\text{ V}$, $-V_I=1\text{ V}$, $I_{SINK} = 4\text{ mA}$	5 V	–	0.12	0.4	–	0.12	0.4	V
Output Leakage Current, I_{OL}	15 V	–	100	–	–	100	–	pA
	36 V	–	500	–	–	500	–	
Response Time $R_L=5.1\text{ k}\Omega$ Rising Edge	15 V	–	1.2	–	–	1.2	–	μs
		Falling Edge	–	200	–	–	200	–
Common-Mode Rejection Ratio, CMRR	$\pm 15\text{ V}$	–	44	316	–	44	562	$\mu\text{V/V}$
	5 V	–	100	316	–	100	562	
Power-Supply Rejection Ratio, PSRR	$\pm 15\text{ V}$	–	15	316	–	15	316	$\mu\text{V/V}$
Large-Signal Response Time $R_L=5.1\text{ k}\Omega$	15 V	–	500	–	–	500	–	ns
	5 V	–	400	–	–	400	–	

Voltage Comparators
CA3290, CA3290A, CA3290B

ELECTRICAL CHARACTERISTICS AT $T_A = 25^\circ\text{C}$

CHARACTERISTIC	TEST COND. V^+	LIMITS			UNITS
		CA3290			
		Min.	Typ.	Max.	
Input Offset Voltage, V_{IO} $V_{CM}=1.4\text{ V}$ $V_O=1.4\text{ V}$	5 V	–	7.5	20	mV
	$V_{CM}=0\text{ V}$ $V_O=0\text{ V}$	$\pm 15\text{ V}$	–	7.5	
Input Current, I_I $V_{CM}=1.4\text{ V}$	5 V	–	3.5	50	pA
	$V_{CM}=0\text{ V}$	$\pm 15\text{ V}$	–	12	
Input Offset Current, I_{IO} $V_{CM}=1.4\text{ V}$	5 V	–	2	30	pA
	$V_{CM}=0\text{ V}$	$\pm 15\text{ V}$	–	7	
Common-Mode Input-Voltage Range, V_{ICR} $V_O=1.4\text{ V}$	5 V	$V^+ - 3.5$ V^-	$V^+ - 3.1$ $V^- - 1.5$	–	V
	$V_O=0\text{ V}$	$\pm 15\text{ V}$	$V^+ - 3.8$ V^-	$V^+ - 3.4$ $V^- - 1.6$	
Supply Current, I^+ $R_L = \infty$	30 V	–	1.35	3	mA
	5 V	–	0.8	1.4	
Voltage Gain, A_{OL} $R_L = 15\text{ k}\Omega$	$\pm 15\text{ V}$	25	800	–	V/mV
		88	118	–	dB
Output Sink Current $V_O=1.4\text{ V}$	5 V	6	30	–	mA
Saturation Voltage $+V_I=0\text{ V}$, $-V_I=1\text{ V}$, $I_{SINK} = 4\text{ mA}$	5 V	–	0.12	0.4	V
Output Leakage Current, I_{OL}	15 V	–	100	–	pA
	36 V	–	500	–	
Response Time $R_L=5.1\text{ k}\Omega$ Rising Edge	15 V	–	1.2	–	μs
		Falling Edge	–	200	–
Common-Mode Rejection Ratio, CMRR	$\pm 15\text{ V}$	–	44	562	$\mu\text{V/V}$
	5 V	–	100	562	
Power-Supply Rejection Ratio, PSRR	$\pm 15\text{ V}$	–	15	316	$\mu\text{V/V}$
Large-Signal Response Time $R_L=5.1\text{ k}\Omega$	15 V	–	500	–	ns
	5 V	–	400	–	

Linear Integrated Circuits

CA3290, CA3290A, CA3290B

TERMINAL ASSIGNMENTS

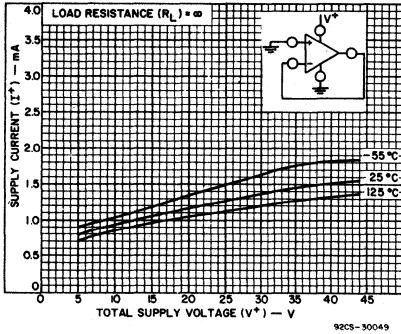
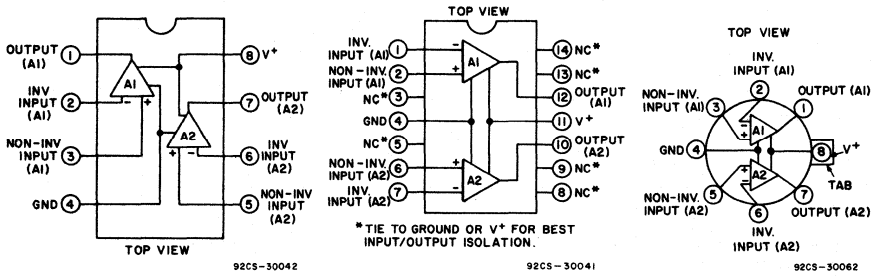


Fig. 3 - Supply current as a function of supply voltage (both amplifiers).

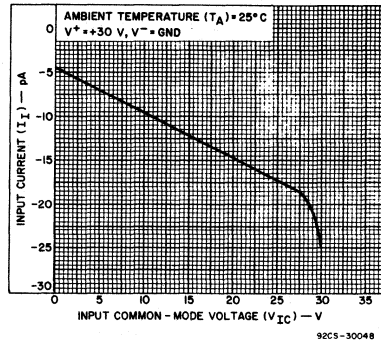


Fig. 4 - Input current as a function of input common-mode voltage.

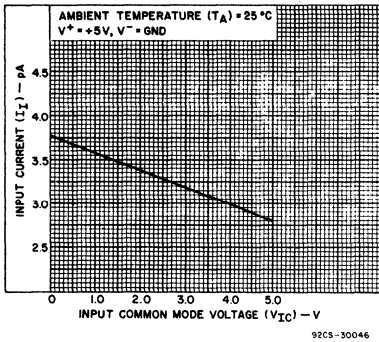


Fig. 5 - Input current as a function of input common-mode voltage.

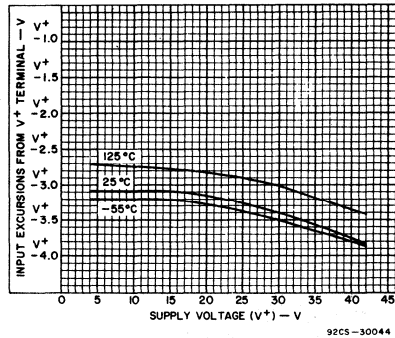


Fig. 6 - Positive common-mode input voltage range as a function of supply voltage.

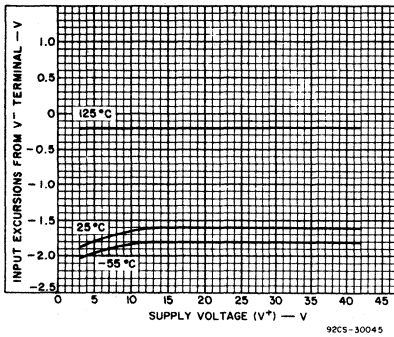


Fig. 7 - Negative common-mode input voltage range as a function of supply voltage.

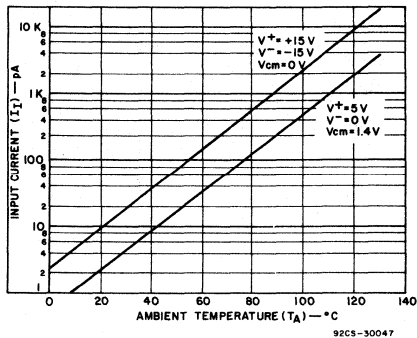


Fig. 8 - Input current as a function of ambient temperature.

CA3290, CA3290A, CA3290B

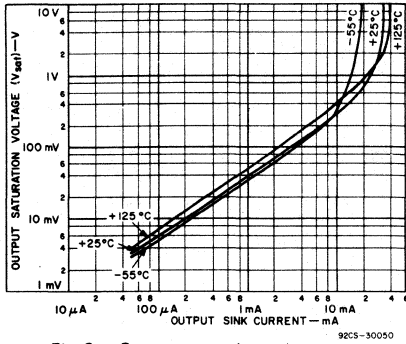
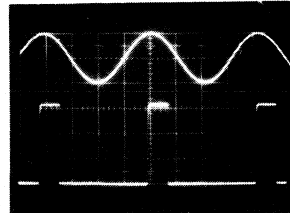
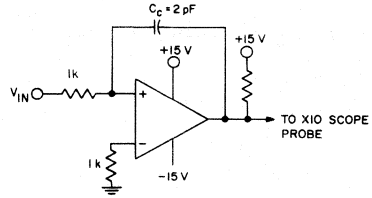
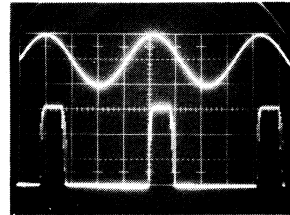


Fig. 9 — Output saturation voltage as a function of output sink current.



WITH C_c
 TOP TRACE ≈ 4.5 mV/DIV = V_{IN}
 BOTTOM TRACE = 10 V/DIV = V_{OUT}
 H = 5 μ s/DIV



WITHOUT C_c
 TOP TRACE ≈ 4.5 mV/DIV
 BOTTOM TRACE = 10 V/DIV
 H = 5 μ s/DIV

92CM-30059R1

Fig. 10 — Parasitic-oscillations test circuit and associated waveforms.

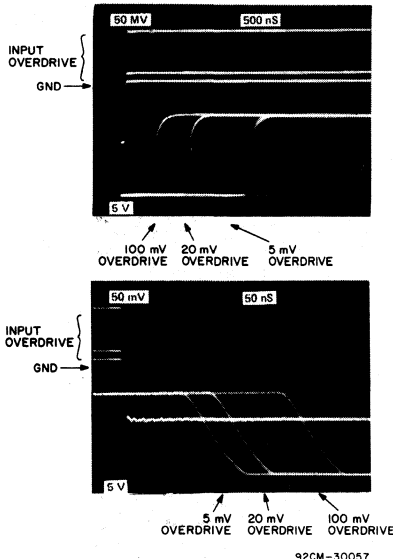
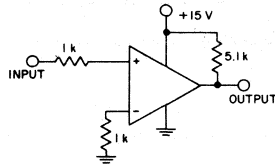


Fig. 11 — Non-inverting comparator response-time test circuit and waveforms.

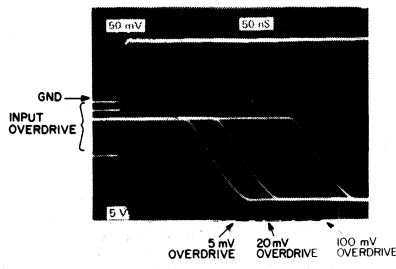
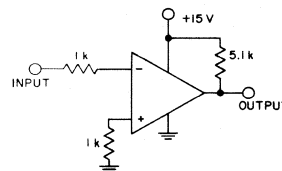


Fig. 12 — Inverting comparator response-time test circuit and waveforms.

OPERATING CONSIDERATIONS

Input Circuit

The use of MOS transistors in the input stage of the CA3290 series circuits provides the user with the following features for comparator applications:

1. Ultra-high input impedance ($\cong 1.7 \text{ T}\Omega$);
2. The availability of common-mode rejection for input signals at potentials below that of the negative power-supply rail;
3. Retention of the in-phase relationship of the input and output signals for input signals below the negative rail.

Although the CA3290 employs rugged bipolar (zener) diodes for protection of the input circuit, the input-terminal currents should not exceed 1 mA. Appropriate series-connected limiting resistors should be used in circuits where greater current flows might exist, allowing the signal input voltage to be greater than the supply voltage without damaging the circuit.

Output Circuit

The output of the CA3290 is the open collector of an n-p-n transistor, a feature providing flexibility in a broad range of comparator applications. An output ORing function can be implemented by parallel-connection of the open collectors. An output pull-up resistor can be connected to a power supply having a voltage range within the rating of the particular CA3290 in use; the magnitude of this voltage may be set at a value which is independent of that applied to the V^+ terminal of the CA3290.

Parasitic Oscillations

The ideal comparator has, among other features, ultra-high input impedance, high gain, and wide bandwidth. These desirable characteristics may, however, produce parasitic oscillations unless certain precautions are observed to minimize the stray capacitive

coupling between the input and output terminals. Parasitic oscillations manifest themselves during the output voltage transition intervals as the comparator switches states. For high source impedances, stray capacitance can induce parasitic oscillations. The addition of a small amount (1 to 10 mV) of positive feedback (hysteresis) produces a faster transition, thereby reducing the likelihood of parasitic oscillations. Furthermore, if the input signal is a pulse waveform, with relatively rapid rise and fall times, parasitic tendencies are reduced.

When dual comparators, like the CA3290, are packaged in an 8-lead configuration, the output terminal of each comparator is adjacent to an input terminal. The lead-to-lead capacitance is approximately 1 pF, which may be sufficient to cause undesirable feedback effects in certain applications. Circuit factors such as impedance levels, supply voltage, toggling rate, etc., may increase the possibility of parasitic oscillations. To minimize this potential oscillatory condition, it is recommended that for source impedances greater than 1 k Ω a capacitor ($\geq 1\text{-}2 \text{ pF}$) be connected between the appropriate input terminal and the output terminal. (See Fig. 10.)

The CA3290A and CA3290 are also supplied in a 14-lead dual-in-line plastic package. To minimize the possibility of parasitic oscillations the input and output terminals are positioned on opposite sides of the package. In addition, there are two leads between the output terminal of each comparator and its corresponding inverting input terminal, reducing the input/output coupling significantly. These leads (8, 9, 13, 14) should be tied to either the V^+ or V^- supply rail. If either comparator is unused, its input terminals should also be tied to either the V^+ or V^- supply rail.

TYPICAL APPLICATIONS

Light-Controlled One-Shot Timer

In Fig. 13 one comparator (A1) of the CA3290 is used to sense a change in photo diode current. The other comparator (A2) is configured as a one-shot timer and is triggered by the output of A1. The output of the circuit will switch to a low state for approximately 60 seconds after the light source to the photo diode has been interrupted. The circuit operates at normal room lighting levels. The sensitivity of the circuit may be adjusted by changing the values of R1 and R2. The ratio of R1 to R2 should be

constant to insure constant reverse voltage bias on the photo diode.

Low-Frequency Multivibrator

In this application, one-half of the CA3290 is used as a conventional multivibrator circuit. Because of the extremely high input impedance of this device, large values of timing resistor (R1) may be used for long time delays with relatively small leakage timing capacitors. The second half of the CA3290 is used as an output buffer to insure that the multivibrator frequency will not be affected by output loading.

Voltage Comparators

CA3290, CA3290A, CA3290B

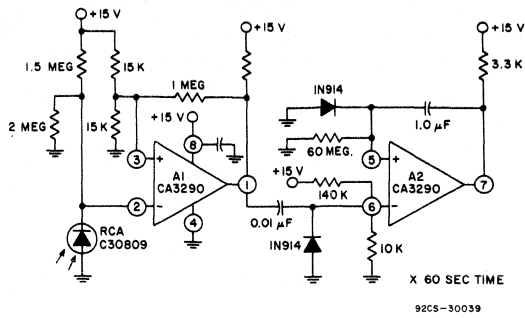


Fig. 13 - Light-controlled one-shot timer.

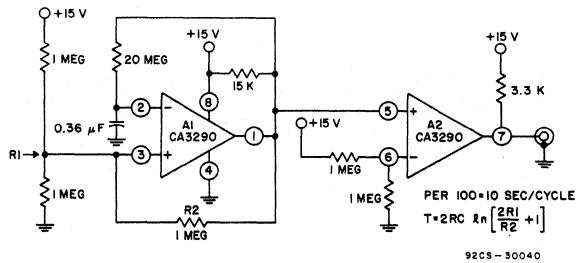


Fig. 14 - Low-frequency multivibrator.

Window Comparator

Both halves of the CA3290 can be used in a high input-impedance window comparator as shown in Fig. 15. The LED will be

turned "on" whenever the input signal is above the lower limit (V_L) but below the upper limit (V_U), as determined by the $R_1/R_2/R_3$ resistor divider.

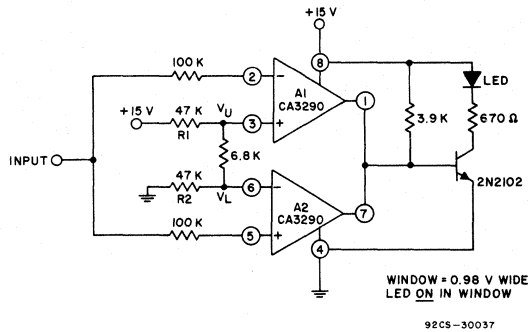


Fig. 15 - Window comparator.

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CA3290, CA3290A, CA3290B

LED Bar Graph Driver

The circuit in Fig. 16 demonstrates the use of the CA3290 in a bar graph display. The non-inverting inputs of both comparators are tied to the voltage divider reference and the input signal is applied to both of the

inverting inputs. The LED for a particular comparator will be turned "on" when the input voltage reaches the voltage on the resistor divider reference. The CA3290 is ideal for this application where input-signal loading is critical even though many comparator inputs are driven in parallel.

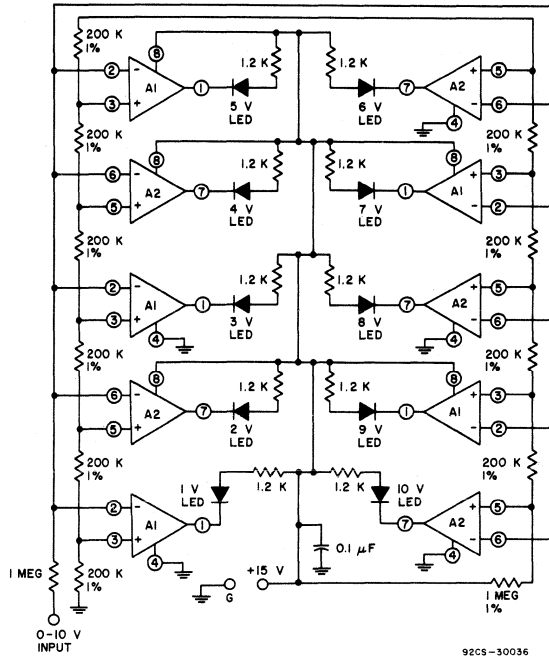
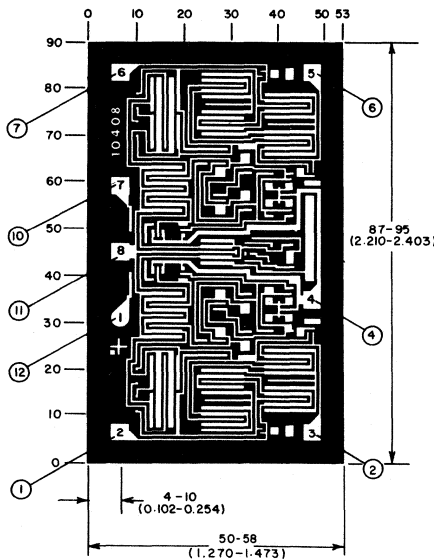


Fig. 16 - LED bar-graph driver.



NOTE NOS. IN PADS ARE FOR 8-LEAD DIP AND T0-5 NOS. OUTSIDE OF CHIP ARE FOR 14-LEAD DIP

92CM-30091

Dimensions and pad layout for the CA3290H.

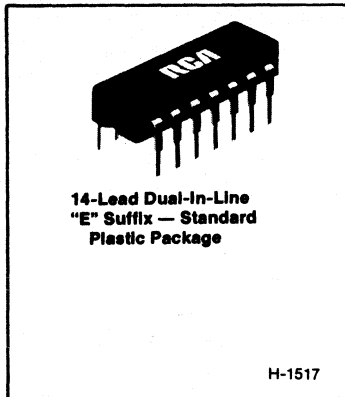
The photographs and dimensions of each COS/MOS chip represent a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

CA139, CA239, CA339 Types

Quad Voltage Comparators

For Industrial, Commercial, and Military Applications

"E" Suffix Types — Standard Dual-In-Line
Plastic Package

Features:

- Operation from single or dual supplies
- Common-mode input-voltage range to ground
- Output voltage compatible with TTL, DTL, ECL, MOS and CMOS
- Differential input-voltage range equal to the supply voltage
- Maximum input-offset voltage (V_{io}):
 - CA139A, CA239A, CA339A — 2 mV
 - CA139, CA239, CA339 — 5 mV
- Replacement for industry types 139, 239, 339, 139A, 239A, and 339A

The RCA-CA139, CA239, CA339, CA139A, CA239A, and CA339A types consist of four independent single- or dual-supply voltage comparators on a single monolithic substrate. The common-mode input voltage range includes ground even when operated from a single supply, and the low power supply current drain makes these comparators suitable for battery operation. These types were designed to directly interface with TTL and CMOS.

Types CA139A, CA239A, and CA339A have all the features and characteristics of their prototype counter parts CA139, CA239, and CA339 plus an even lower input-offset-voltage characteristic. These devices are supplied in a 14-lead dual-in-line plastic package (E suffix). The CA339 is also available in chip form (H suffix).

Applications:

- Square-wave generators
- Time-delay generators
- Pulse generators
- Multivibrators
- High-voltage digital logic gates
- A/D converters
- MOS clock timers

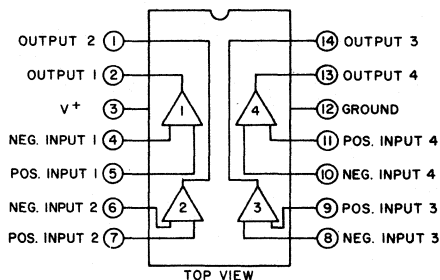


Fig. 1 - Functional diagram.

Linear Integrated Circuits

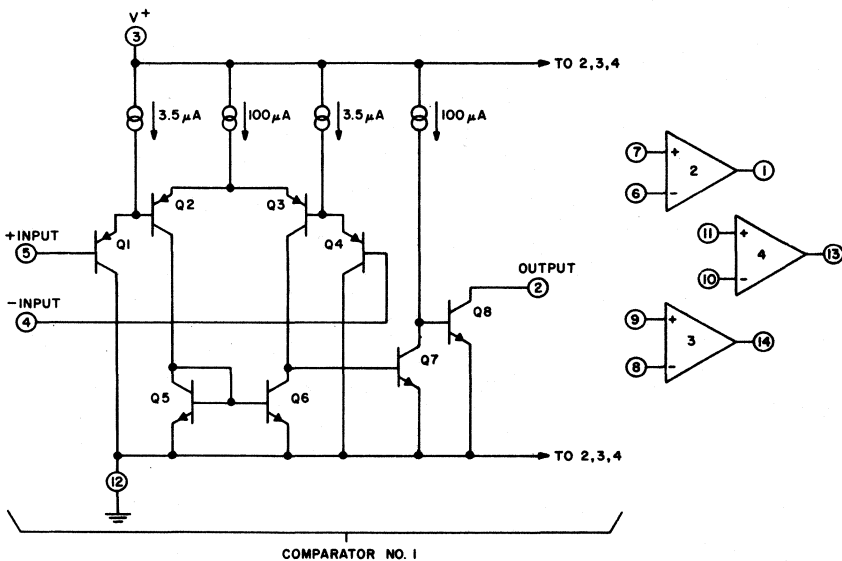
CA139, CA239, CA339 Types

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$:

DC SUPPLY VOLTAGE	36 V or ± 18 V
DC DIFFERENTIAL INPUT VOLTAGE	± 36 V
INPUT VOLTAGE	-0.3 V to +36 V
INPUT CURRENT ($V_I < -0.3$ V)*	50 mA
OUTPUT SHORT CIRCUIT TO GROUND [▲]	
(Single Supply)	Continuous
DEVICE DISSIPATION:	
Up to $T_A = 55^\circ\text{C}$	750 mW
Above $T_A = 55^\circ\text{C}$	derate linearly at 6.67 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:	
Operating	-55 to +125 $^\circ\text{C}$
Storage	-65 to +150 $^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance $1/16 \pm 1/32$ in. (1.59 ± 0.79 mm)	
from case for 10 seconds max.	+265 $^\circ\text{C}$

* Inputs must not go more negative than -0.3 V.

▲ Short circuits from the output to V^+ can cause excessive heating and eventual destruction. The maximum output current independent of V^+ is approximately 20 mA.



92CM-24150R1

Fig. 2—Schematic diagram.

Voltage Comparators

CA139, CA239, CA339 Types

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	TEST CONDITIONS		LIMITS						UNITS
	V ⁺ = 5 V Unless otherwise indicated		CA139			CA139A			
			Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage (V _{IO}) At Output Switch Point V ≅ 1.4 V	V _{REF} = 1.4 V, R _S = 0	25°C	–	2	5	–	1	2	mV
		Note 1	–	–	9	–	–	4	
Differential Input Voltage (V _{ID})	Keep all inputs ≥ 0 V for V [–] (If used), Notes 1, 2		–	–	36	–	–	36	V
Saturation Voltage (V _{sat})	V _I [–] = 1 V, V _I ⁺ = 0 V, I _{SINK} ≤ 4 mA	25°C	–	250	400	–	250	400	mV
		Note 1	–	–	700	–	–	700	
Common-Mode Input Voltage Range (V _{ICR})	Note 3	25°C	0	–	V ⁺ –1.5	0	–	V ⁺ –1.5	V
		Note 1	0	–	V ⁺ –2	0	–	V ⁺ –2	
Input Offset Current (I _{IO})	I _I ⁺ – I _I [–]	25°C	–	3	25	–	3	25	nA
		Note 1	–	–	100	–	–	100	
Input Bias Current (I _{IB})	I _I ⁺ or I _I [–] with Output in Linear Range	25°C	–	25	100	–	25	100	nA
		Note 1	–	–	300	–	–	300	
Supply Current (I ⁺)	R _L = ∞ on all comparators, T _A = 25°C		–	0.8	2	–	0.8	2	mA
Output Leakage Current	V _I ⁺ ≥ 1 V, V _I [–] = 0, V _O = 5 V	25°C	–	0.1	–	–	0.1	–	nA
	V _I ⁺ ≥ 1 V, V _I [–] = 0, V _O = 30 V	Note 1	–	–	1	–	–	1	μA
Output Sink Current	V _I [–] ≥ 1 V, V _I ⁺ = 0, V _O ≤ +1.5 V, T _A = 25°C		6	16	–	6	16	–	mA
Voltage Gain (A _{OL})	R _L ≥ 15 kΩ, V ⁺ = 15 V, T _A = 25°C		–	200	–	50	200	–	V/mV
Large Signal Response Time	V _I = TTL Logic Swing, V _{REF} = +1.4 V, V _{RL} = 50 V, R _L = 5.1 kΩ, T _A = 25°C		–	300	–	–	300	–	ns
Response Time See Figs. 5 & 6	V _{RL} = 5 V, R _L = 5.1 kΩ, T _A = 25°C		–	1.3	–	–	1.3	–	μs

Note 1: Ambient Temperature (T_A) applicable over operating temperature range as shown below.

CA139 (–55 to +125°C)	CA239 (–25 to +85°C)	CA339 (0 to +70°C)
CA139A	CA239A	CA339A

Note 2: The comparator will provide a proper output state even if the positive swing of the inputs exceeds the power supply voltage level, if the other input remains within the common-mode voltage range. The low input voltage state must not be less than –0.3 V (or 0.3 V below the magnitude of the negative power supply, if used).

Note 3: The upper end of the common-mode voltage range is (V⁺) – 1.5 V, but either or both inputs can go to +30 V without damage.

Linear Integrated Circuits

CA139, CA239, CA339 Types

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	TEST CONDITIONS		LIMITS						UNITS
	V ⁺ = 5 V		CA239, CA339			CA239A, CA339A			
	Unless otherwise indicated		Min.	Typ.	Max.	Min.	Typ.	Max.	
Input Offset Voltage (V _{IO}) At Output Switch Point V ≅ 1.4 V	V _{REF} = 1.4 V, R _S = 0	25°C	–	2	5	–	1	2	mV
		Note 1	–	–	9	–	–	4	
Differential Input Voltage (V _{ID})	Keep all inputs ≥ 0 V for V [–] (If used), Notes 1, 2		–	–	36	–	–	36	V
Saturation Voltage (V _{sat})	V _I [–] = 1 V, V _I ⁺ = 0 V, I _{SINK} ≤ 4 mA	25°C	–	250	400	–	250	400	mV
		Note 1	–	–	700	–	–	700	
Common-Mode Input Voltage Range (V _{ICR})	Note 3	25°C	0	–	V ⁺ – 1.5	0	–	V ⁺ – 1.5	V
		Note 1	0	–	V ⁺ – 2	0	–	V ⁺ – 2	
Input Offset Current (I _{IO})	I _I ⁺ – I _I [–]	25°C	–	5	50	–	5	50	nA
		Note 1	–	–	150	–	–	150	
Input Bias Current (I _{IB})	I _I ⁺ or I _I [–] with Output in Linear Range	25°C	–	25	250	–	25	250	nA
		Note 1	–	–	400	–	–	400	
Supply Current (I ⁺)	R _L = ∞ on all comparators, T _A = 25°C		–	0.8	2	–	0.8	2	mA
Output Leakage Current	V _I ⁺ ≥ 1 V, V _I [–] = 0, V _O = 5 V	25°C	–	0.1	–	–	0.1	–	nA
		Note 1	–	–	1	–	–	1	μA
Output Sink Current	V _I [–] ≥ 1 V, V _I ⁺ = 0, V _O ≤ +1.5 V, T _A = 25°C		6	16	–	6	16	–	mA
Voltage Gain (A _{OL})	R _L ≥ 15 kΩ, V ⁺ = 15 V, T _A = 25°C		–	200	–	50	200	–	V/mV
Large Signal Response Time	V _I = TTL Logic Swing, V _{REF} = +1.4 V, V _{RL} = 50 V, R _L = 5.1 kΩ, T _A = 25°C		–	300	–	–	300	–	ns
Response Time See Figs. 5 & 6	V _{RL} = 5 V, R _L = 5.1 kΩ, T _A = 25°C		–	1.3	–	–	1.3	–	μs

Note 1: Ambient Temperature (T_A) applicable over operating temperature range as shown below.

CA139 (–55 to +125°C) CA239 (–25 to +85°C) CA339 (0 to +70°C)
CA139A CA239A CA339A

Note 2: The comparator will provide a proper output state even if the positive swing of the inputs exceeds the power supply voltage level, if the other input remains within the common-mode voltage range. The low input voltage state must not be less than –0.3 V (or 0.3 V below the magnitude of the negative power supply, if used).

Note 3: The upper end of the common-mode voltage range is (V⁺) – 1.5 V, but either or both inputs can go to +30 V without damage.

Voltage Comparators CA139, CA239, CA339 Types

TYPICAL CHARACTERISTICS

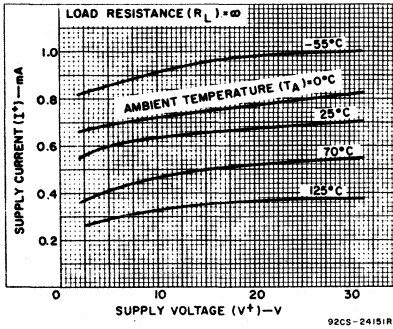


Fig. 3—Supply current vs. supply voltage.

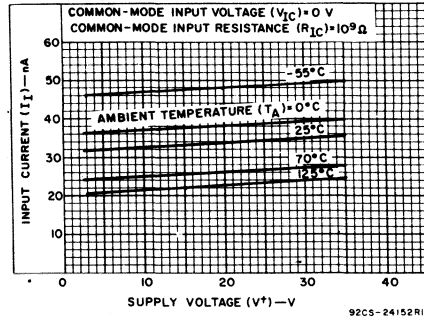


Fig. 4—Input current vs. supply voltage.

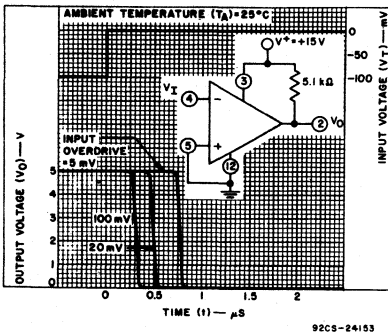


Fig. 5—Response time for various input overdrives—negative transition.

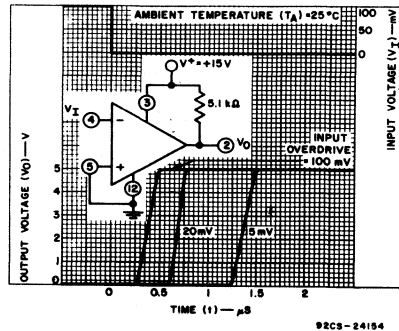


Fig. 6—Response time for various input overdrives—positive transition.

Chip Version (CA339H)

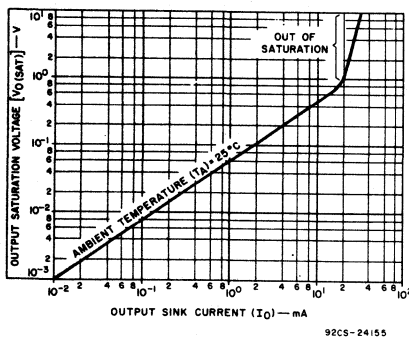
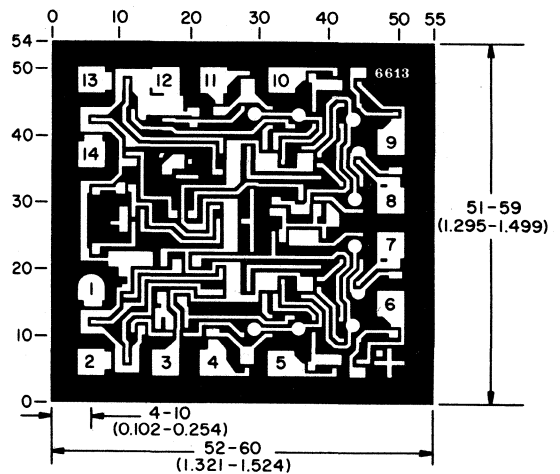


Fig. 7—Output saturation voltage vs. output sink current.



92CS-33255

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

Data Conversion Circuits

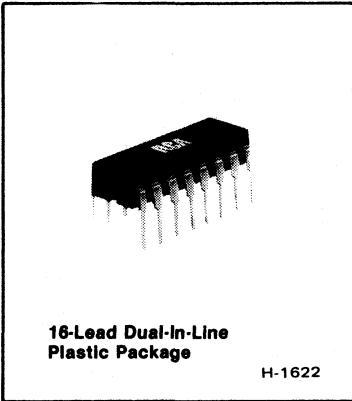
Technical Data

A/D Converters	Page
CA3162	308
CA3300	316
CA3308	327

Display Drivers	
CA3081	332
CA3082	332
CA3161	335
CA3168	339
CA3207*	343
CA3208*	343

*BIMOS types

CA3162E



A/D Converter for 3-Digit Display

Features:

- Dual-slope A/D conversion
- Multiplexed BCD display
- Ultra-stable internal band-gap voltage reference
- Capable of reading 99 mV below ground with single supply
- Differential input
- Internal timing - no external clock required

- Choice of low-speed [4-Hz] or high-speed [96-Hz] conversion rate
- "Hold" inhibits conversion but maintains delay
- Overrange indication - "EEE" for reading greater than + 999 mV, "-" for reading more negative than -99 mV when used with CA3161E BCD-to-Seven Segment Decoder/Driver

The CA3162E is an I²L monolithic A/D converter that provides a 3-digit multiplexed BCD output. It is used with the CA3161E BCD-to-Seven-Segment Decoder/Driver* and a minimum of external parts to implement a complete 3-digit display.

The CA3162 is supplied in 16-lead dual-in-line plastic package (E suffix). The CA3162 is also available in chip form (H suffix).

*The CA3161E is described in RCA data bulletin File No. 1079.

TERMINAL ASSIGNMENT
CA3162E

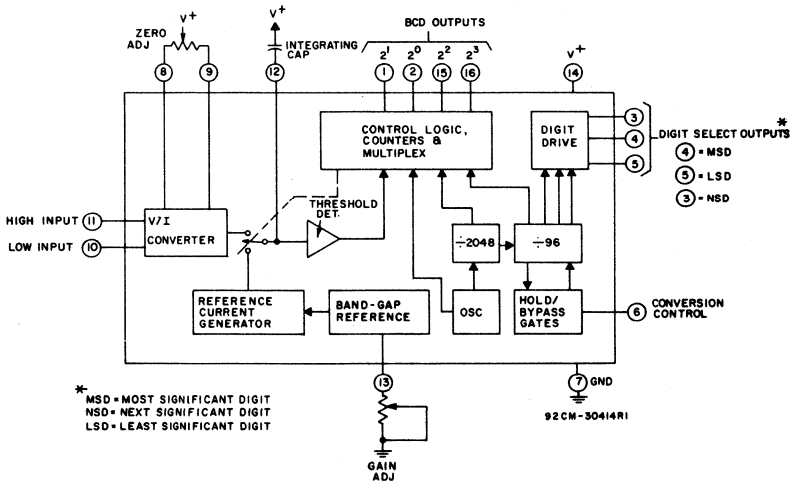
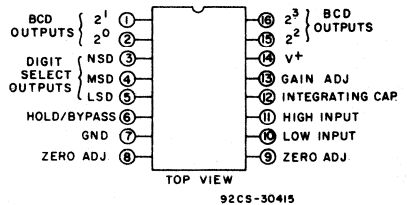


Fig. 1 — Functional block diagram of the CA3162E.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE (between terminals 7 and 14) +7 V
 INPUT VOLTAGE (terminal 10 or 11 to ground) ±15 V
 DEVICE DISSIPATION:
 Up to $T_A = +55^\circ\text{C}$ 750 mW
 Above $T_A = +55^\circ\text{C}$ derate linearly at 7.9 mW/ $^\circ\text{C}$
 AMBIENT TEMPERATURE RANGE:
 Operating 0 to +75 $^\circ\text{C}$
 Storage -65 to +150 $^\circ\text{C}$
 LEAD TEMPERATURE (DURING SOLDERING):
 At distance 1/16 ± 1/32 inch (1.59 ± 0.79 mm) from case for 10 seconds max. +265 $^\circ\text{C}$

**ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V^+ = 5\text{ V}$, Zero pot centered,
gain pot = 2.4 k Ω unless otherwise stated**

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
Operating Supply Voltage Range, V^+		4.5	5	5.5	V
Supply Current, I^+	100 k Ω to V^+ on terms. 3,4,5	—	—	17	mA
Input Impedance, Z_I		—	100	—	M Ω
Input Bias Current, I_{IB}	Terms. 10 and 11	—	-80	—	nA
Unadjusted Zero Offset	$V_{11} - V_{10} = 0\text{ V}$, read decoded output	-12	—	+12	mV
Unadjusted Gain	$V_{11} - V_{10} = 900\text{ mV}$, read decoded output	846	—	954	mV
Linearity	See Notes 1 and 2	-1	—	+1	Count
Conversion Rate:					
Slow Mode	Term. 6 = open or gnd	—	4	—	Hz
Fast Mode	Term. 6 = 5 V	—	96	—	
Conversion Control Voltage (Hold Mode) at Terminal 6		0.8	1.2	1.6	V
Common-Mode Input Voltage Range, V_{ICR}	See Note 3, 4	-0.2	—	+0.2	V
BCD Sink Current at terms. 1,2,15,16	$V_{BCD} \geq 0.5\text{ V}$, at logic zero state	0.4	1.6	—	mA
Digit Select Sink Current at terms. 3,4,5	$V_{\text{Digit Select}} = 4\text{ V}$ at logic zero state	1.6	2.5	—	mA
Zero Temperature Coefficient	$V_I = 0\text{ V}$, zero pot centered	—	10	—	$\mu\text{V}/^\circ\text{V}$
Gain Temperature Coefficient	$V_I = 900\text{ mV}$, gain pot = 2.4 k Ω	—	0.005	—	%/ $^\circ\text{C}$

Notes:

1. Apply zero volts across V_{11} to V_{10} . Adjust zero potentiometer to give 000 mV reading. Apply 900 mV to input and adjust gain potentiometer to give 900 mV reading.
2. Linearity is measured as a difference from a straight line drawn through zero and positive full scale. Limits do not include ±0.5 count bit digitizing error.
3. For applications where negative terminal 10 is not operated at terminal 7 potential, a return path of not more than 100 k Ω resistance must be provided for input bias currents.
4. The common-mode input voltage above ground cannot exceed +0.2 V if the full input signal range of 999 mV is required at terminal 11. That is, terminal 11 may not operate higher than 1.2 V positive with respect to ground or 0.2 V negative with respect to ground. If the maximum input signal is less than 999 mV, the common-mode input voltage may be raised accordingly.

CA3162E

Circuit Description

The functional block diagram of the CA3162E is shown in Fig. 1. The heart of the system is the V/I converter and reference-current generator. The V/I converter converts the input voltage applied between terminals 10 and 11 to a current that charges the integrating capacitor on terminal 12 for a predetermined time interval. At the end of the charging interval, the V/I converter is disconnected from the integrating capacitor, and a band-gap reference constant-current source of opposite polarity is connected. The number of clock counts that elapse before the charge is restored to its original value is a direct measure of the signal induced current. The restoration is sensed by the comparator, which in turn latches the counter. The count is then multiplexed to the BCD outputs.

The timing for the CA3162E is supplied by a 786-Hz ring oscillator, and the input at terminal 6 determines the sampling rate. A 5-V input provides a high-speed sampling rate (96 Hz), and grounding or

floating terminal 6 provides a low-speed (4 Hz) sampling rate. When terminal 6 is fixed at +1.2 V (by placing a 12 K resistor between terminal 6 and the +5-V supply) a "hold" feature is available. While the CA3162E is in the hold mode, sampling continues at 4 Hz but the display data are latched to the last reading prior to the application of the 1.2 V. Removal of the 1.2 V restores continuous display changes. Note, however, that the sampling rate remains at 4 Hz.

Fig. 3 shows the timing of sampling and digit select pulses for the high-speed mode. Note that the basic A/D conversion process requires approximately 5 ms in both modes.

The "EEE" or "---" displays indicate that the range of the system has been exceeded in the positive or negative direction, respectively. Negative voltages to -99 mV are displayed with the minus sign in the MSD. The BCD code is 1010 for a negative overrange (---) and 1011 for a positive overrange (EEE).

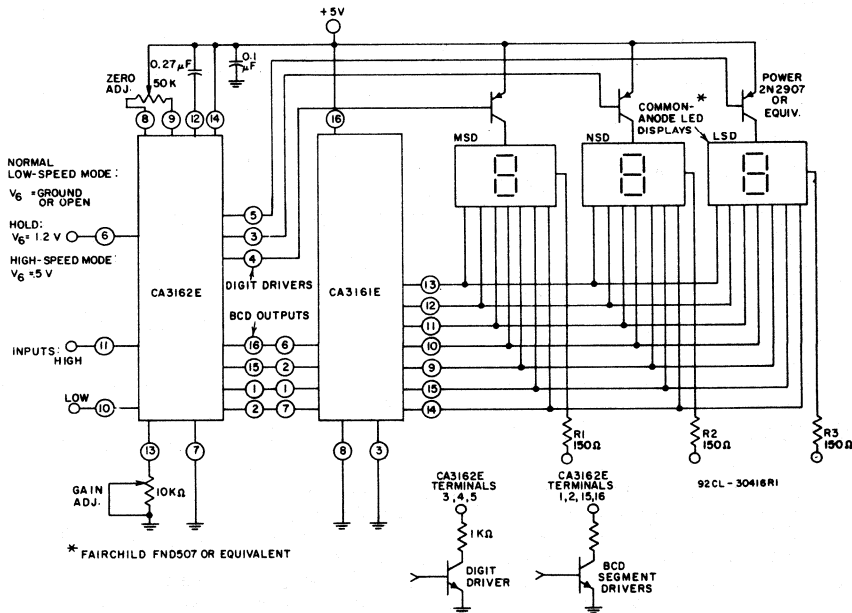


Fig. 2—Basic digital readout system using the CA3162E and the CA3161E.

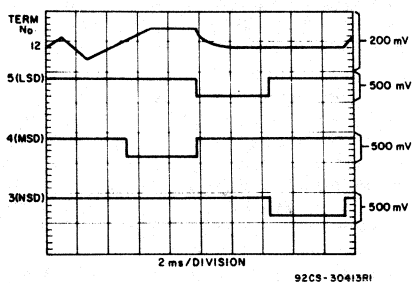


Fig. 3—High speed mode timing diagram.

CA3162E Liquid Crystal Display (LCD) Application

Fig. 4 shows the CA3162E in a typical LCD application. LCD's may be used in

favor of LED displays in applications requiring lower power dissipation, such as battery-operated equipment, or when visibility in high-ambient-light conditions is desired.

Multiplexing of LCD digits is not practical, since LCD's must be driven by an ac signal and the average voltage across each segment is zero. Three CD4056B liquid-crystal decoder/drivers are therefore used. Each CD4056B contains an input latch so that the BCD data for each digit may be latched into the decoder, using the inverted digit-select outputs of the CA3162E as strobes.

Inverters G1 and G2 are used as an astable multivibrator to provide the ac drive to the LCD backplane. Inverters G3, G4, and G5 are the digit-select inverters

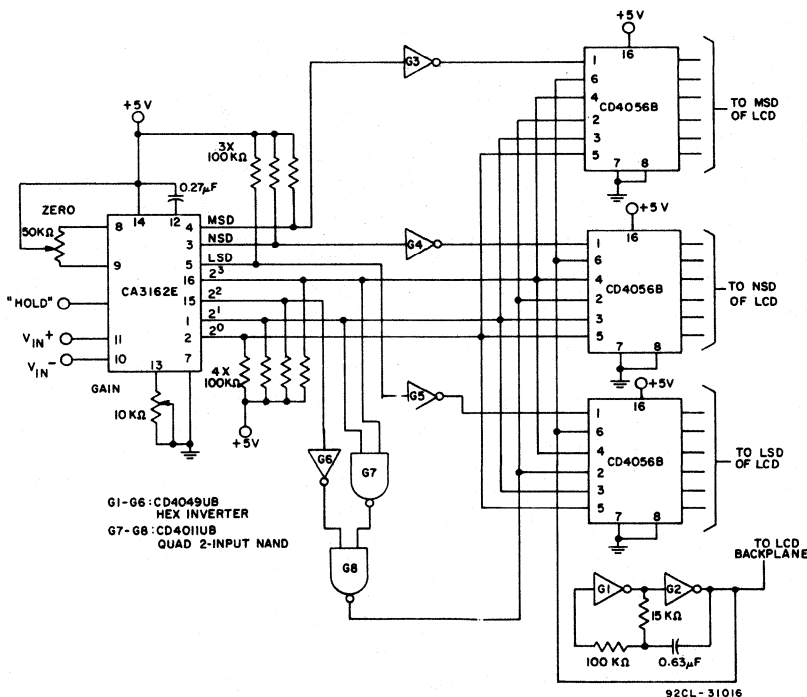


Fig. 4—Typical LCD application.

Linear Integrated Circuits

CA3162E

and require pull-up resistors to interface the open-collector outputs of the CA3162E to COS/MOS logic. The BCD outputs of the CA3162E may be connected directly to the corresponding CD4056B inputs (using pull-up resistors). In this arrangement, the CD4056B decodes the negative sign (—) as an “L” and the positive overload indicator (E) as an “H”.

CA3162E Common-Cathode, LED Display Application

Fig. 5 shows the CA3162E connected to a CD4511B decode/driver to operate a common-cathode LED display. Unlike the CA3161E, the CD4511B remains blank for all BCD codes greater than nine. After 999 mV the display blanks rather than displaying EEE, as with the CA3161E. When

displaying negative voltage, the first digit remains blank instead of (—), and during a negative or positive overrange the display blanks.

The additional logic shown within the dotted area of Fig. 5 restores the negative sign (—), allowing the display of negative numbers as low as -99 mV. Negative overrange is indicated by a negative sign (—) in the MSD position. The rest of the display is blanked. During a positive overrange, only segment b of the MSD is displayed. One inverter from the CD4049B is used to operate the decimal points. By connecting the inverter input to either the MSD or NSD line either DP1 or DP2 will be displayed. Fig. 7 shows the P.C. board and component placement.

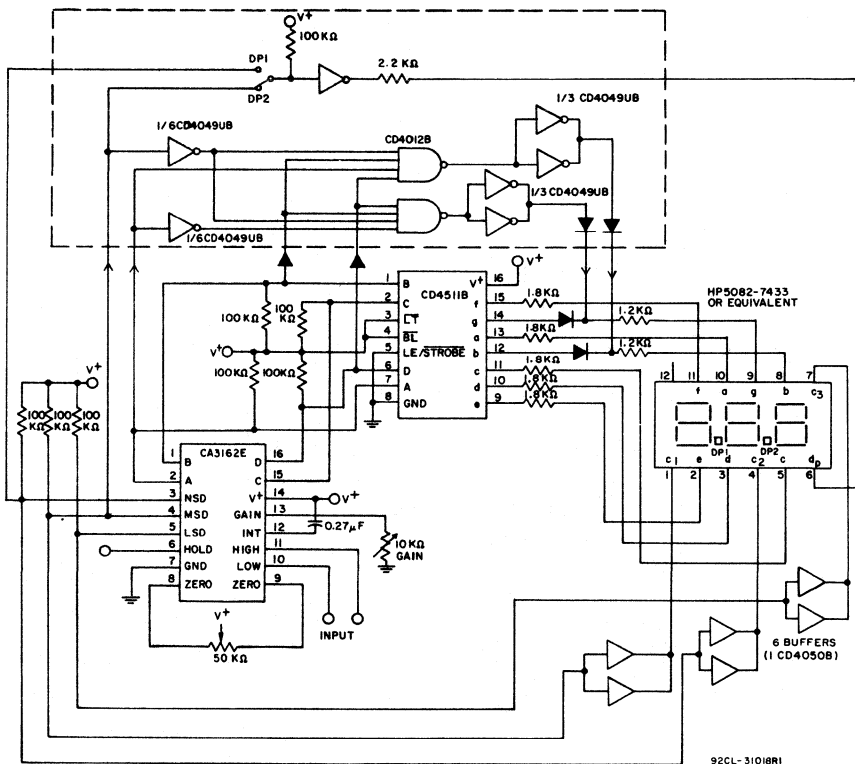
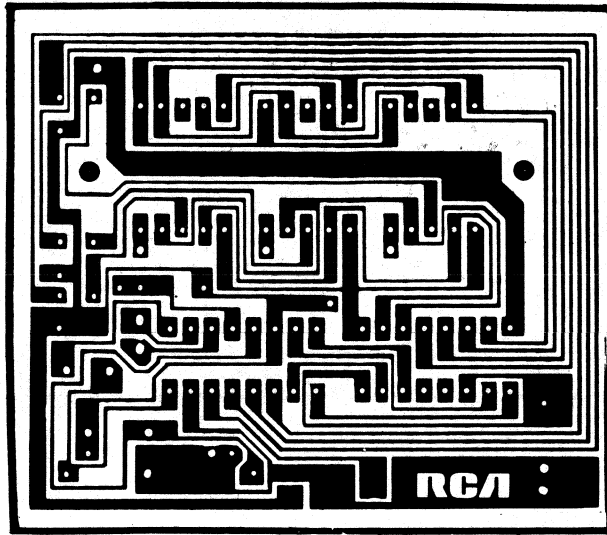
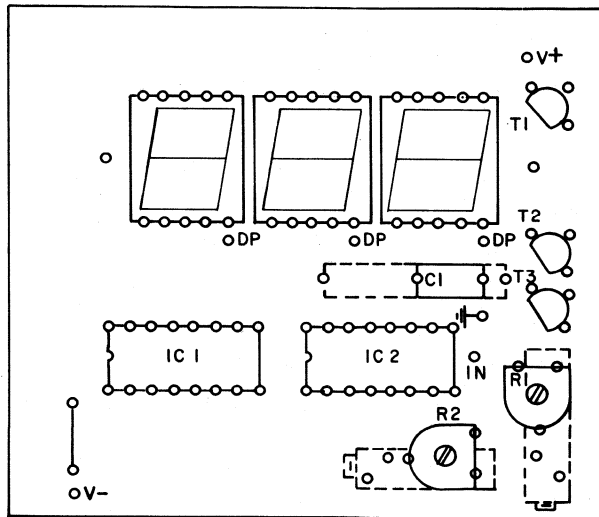


Fig. 5—Typical common-cathode LED application.



92CS-32692



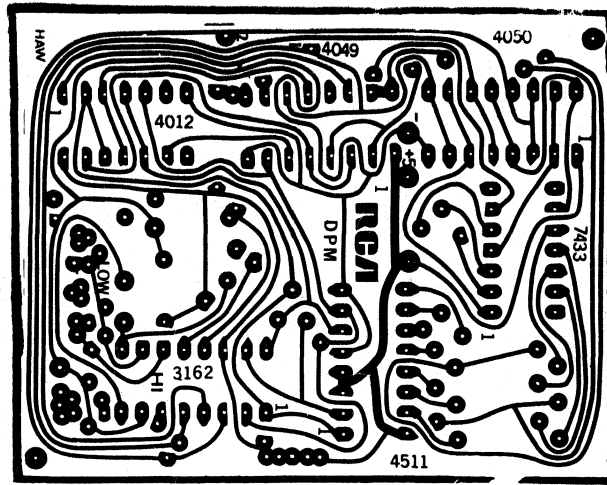
92CS- 32693

Fig. 6—P.C. board* template (actual size $\pm 3\%$) and component layout guide for circuit shown in Fig. 2.

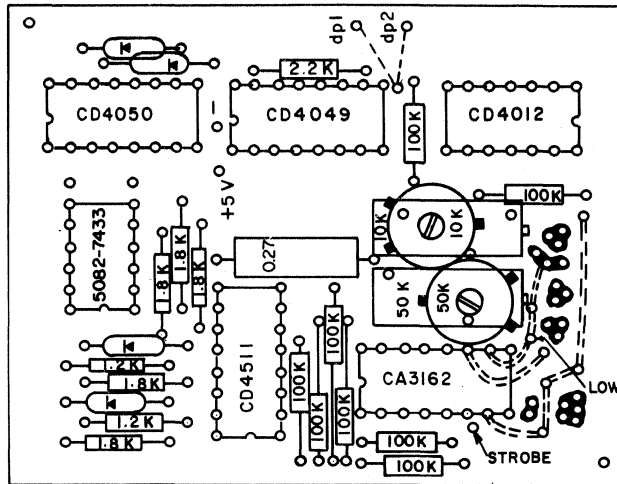
*P.C. board courtesy ETS. Velleman P.V.B.A., St. Amandsberg, Belgium

Linear Integrated Circuits

CA3162E

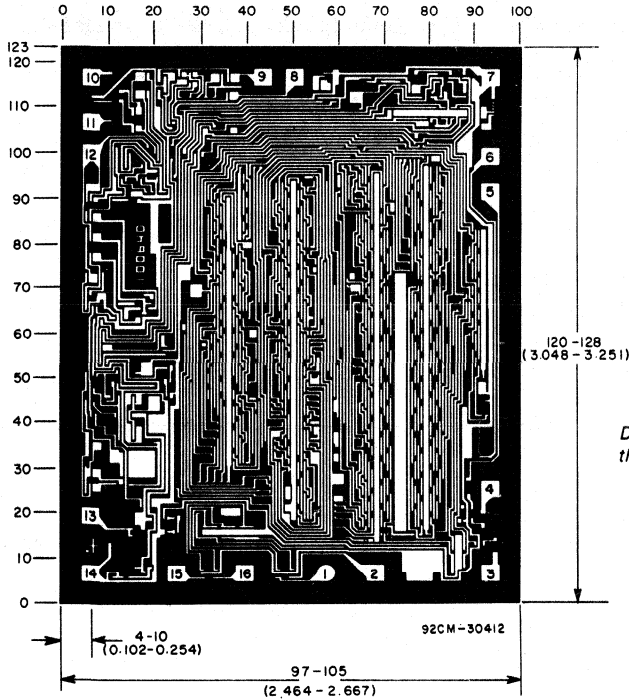


92CS-32691



92CS-32694

Fig. 7—P.C. board template (actual size $\pm 3\%$) and component layout guide for circuit shown in Fig. 5.

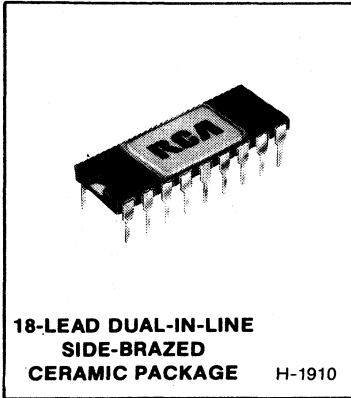


Dimensions and pad layout for the CA3162H Chip.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

The photographs and dimensions of each Linear chip represent a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

CA3300



CMOS Video Speed 6-Bit Flash Analog-to-Digital Converter

For Use in Low-Power Consumption, High-Speed Digitization Applications

FEATURES:

- CMOS low power with speed
- Parallel conversion technique
- 15-MHz sampling rate (66-ns conversion time)
- 6-bit latched 3-state output with overflow bit
- $\pm 1/2$ LSB accuracy
- Single supply voltage (3 to 10 V)
- 2 units in series allow 7-bit output
- 2 units in parallel allow 30-MHz sampling rate
- Internal VREF with ext VREF option

The RCA-CA3300 is a CMOS 50-mW parallel (FLASH) analog-to-digital converter designed for applications demanding both low-power consumption and high-speed digitization.

The CA3300 operates over a wide full-scale input-voltage range of 2.4 volts up to the dc supply voltage with maximum power consumptions as low as 50 to 200 mW, depending upon the clock frequency selected. When operated from a 5-volt supply at a clock frequency of 11 MHz, the power consumption of the CA3300 is less than 50 mW. When operated from an 8-volt supply at a frequency of 15 MHz, the power consumption is less than 150 mW.

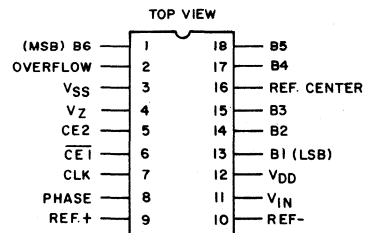
The intrinsic high conversion rate makes the CA3300 ideally suited for digitizing high-speed signals. The overflow bit makes possible the connection of two or more CA3300s in series to increase the resolution of the conversion system. A series connection of two CA3300s may be used to produce a 7-bit high-speed converter. Operation of two CA3300s in parallel doubles the conversion speed (i.e., increases the sampling rate from 15 to 30 MHz). CA3300s in parallel may be combined with a high-speed 6-bit D/A converter, a binary adder, control logic, and an op amp to form a very high-speed A/D converter.

Sixty-four paralleled auto-balanced voltage comparators measure the input voltage with respect to a known reference to produce the parallel-bit outputs in the CA3300. Sixty-three comparators are required to quantize all input voltage levels in this 6-bit converter, and the additional comparator is required for the overflow bit.

The CA3300 type is available in an 18-lead dual-in-line ceramic package (D suffix) or in chip form (H suffix).

APPLICATIONS

- The CA3300 is especially suited for high-speed conversion applications where low power is also important
- TV video digitizing (industrial/security)
- High-speed A/D conversion
- Ultrasound signature analysis
- Transient signal analysis
- High-energy physics research
- High-speed oscilloscope storage/display
- General-purpose hybrid ADCs
- Optical character recognition
- Radar pulse analysis
- Motion signature analysis



92CS-32263RI

TERMINAL ASSIGNMENT

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		MIN.	TYP.	MAX.	
Resolution		—	—	6	Bits
Linearity Error	V _{DD} =8 V, V _{REF} =7.68 V CLK=15 MHz, gain adjusted	—	±0.5	±0.8	LSB
Differential Linearity Error	V _{DD} =8, V _{REF} =7.68 V CLK=15 MHz	—	±0.5	±0.8	
Quantizing Error		-1/2	—	1/2	
Analog Input: Full Scale Range	V _{DD} =8 V CLK=15 MHz	2.4	—	V _{DD} +0.5	V
Input Capacitance		—	50	—	pF
Input Current		—	600	1000	μA
Gain Temperature Coefficient	V _{DD} =8 V, CLK=15 MHz	—	0.016	—	LSB/°C
Maximum Conversion Speed	V _{DD} =5 V V _{DD} =8 V	— 15M	12M 19M	— —	SPS
Device Current (Excludes I _{REF} , I _Z)	V _{DD} =5 V (CLK=11 MHz) V _{DD} =8 V (CLK=15 MHz) V _{DD} =5 V (Auto Balance State) V _{DD} =8 V (Auto Balance State)	— — — —	7 22 6.4 24	— — 16 40	mA
Ladder Impedance		1000	1400	1800	Ω
Digital Inputs:					
Low Voltage	V _{DD} =5 V V _{DD} =8 V	— —	— —	1.5 2.5	V V
High Voltage	V _{DD} =5 V V _{DD} =8 V	3.5 5.5	— —	— —	V V
Input Current	V _{DD} =8 V	—	±1	—	μA
Digital Outputs:					
Output Low (Sink) Current	V _{DD} =5 V, V _O =0.4 V V _{DD} =8 V, V _O =0.5	1.6 3.2	10 15	— —	mA
Output High (Source) Current	V _{DD} =5 V, V _O =4.6 V V _{DD} =8 V, V _O =7.5 V	-0.8 -1.6	6 9	— —	
Zener Voltage	I _Z =10 mA	6.2	6.8	7.4	V
Zener Dynamic Impedance	I _Z =10 mA	—	10	30	Ω
Zener Temperature Coefficient		—	0.5	—	mV/°C
Digital Output Delay, t _d	V _{DD} =8 V	—	20	—	ns
Aperture Time	V _{DD} =8 V	—	25	—	

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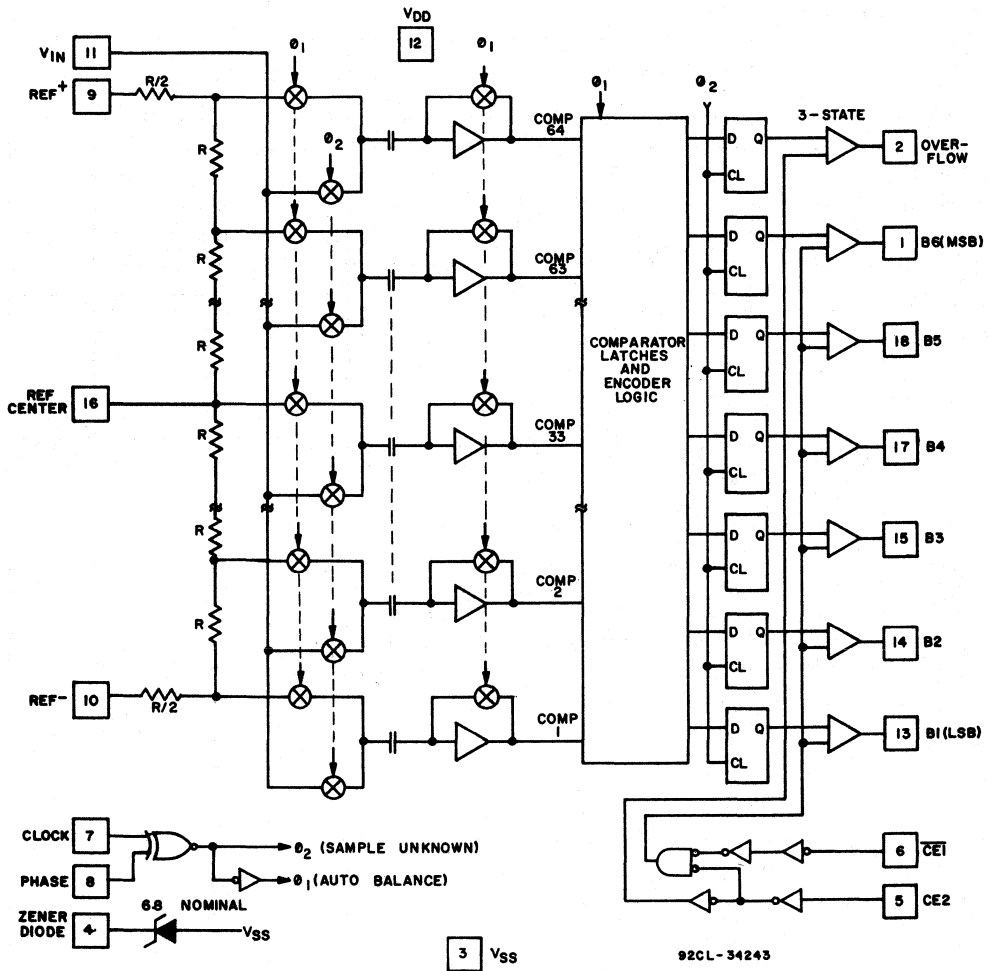
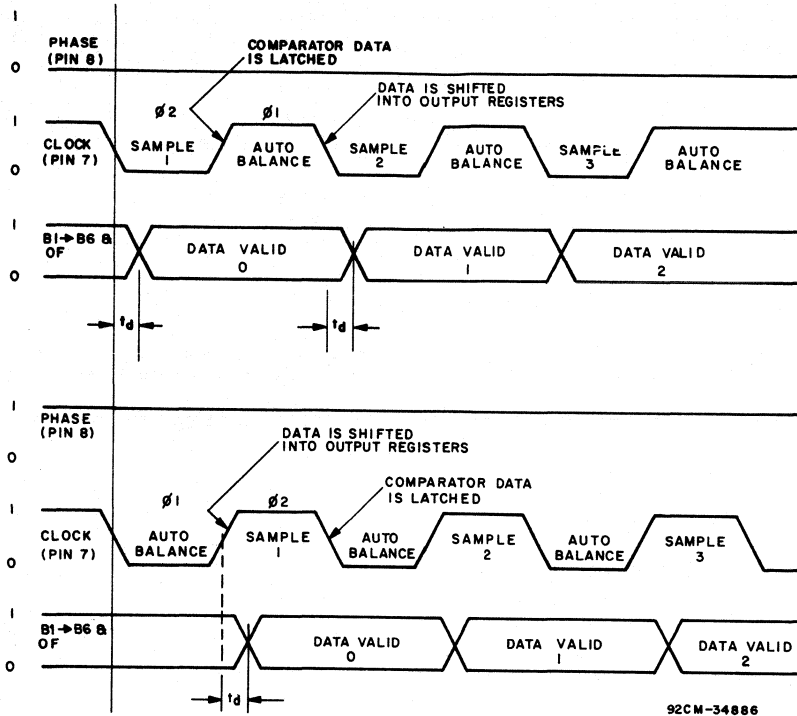


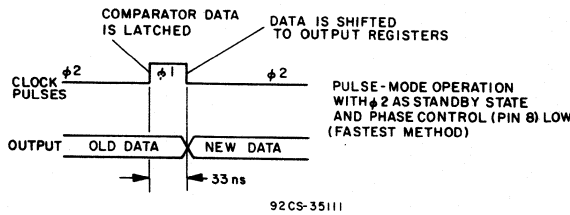
Fig. 1 - Block diagram for the CA3300.

MAXIMUM RATINGS, Absolute-Maximum Values:

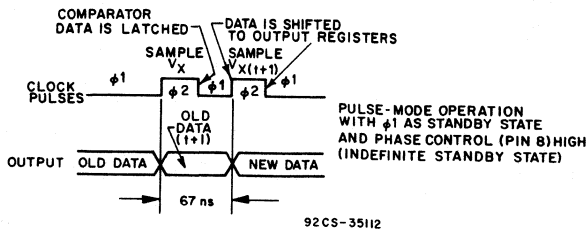
DC SUPPLY VOLTAGE RANGE (V_{DD})	
(VOLTAGE REFERENCED TO V_{SS} TERMINAL)	-0.5 to 10 V
INPUT VOLTAGE RANGE	
ALL INPUTS EXCEPT ZENER (PIN 4)	-0.5 to $V_{DD} + 0.5$ V
DC INPUT CURRENT	
CLK, PH, $\overline{CE1}$, $\overline{CE2}$, V_{IN}	± 10 mA
POWER DISSIPATION PER PACKAGE (P_D)	
FOR $T_A = -40$ to 55°C	315 mW
FOR $T_A = 55^\circ\text{C}$ to 85°C	Derate linearly at 3.3 mW/ $^\circ\text{C}$
TEMPERATURE RANGE	
OPERATING	-40 to $+85^\circ\text{C}$
STORAGE	-65 to $+150^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING)	
AT DISTANCE $1/16 \pm 1/32$ in. (1.59 ± 0.79 mm) FROM CASE FOR 10 s MAX.	$+265^\circ\text{C}$



(a)



(b)



(c)

Fig. 2 - Timing diagrams for the CA3300.

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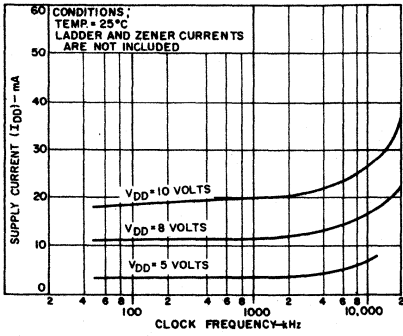


Fig. 3 - Typical current drain versus sampling rate as a function of supply voltage.

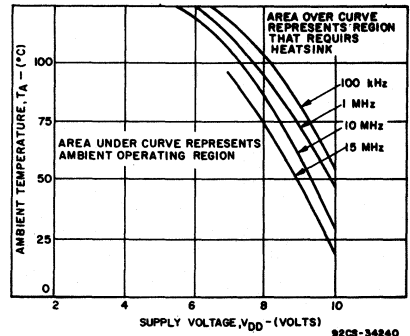


Fig. 4 - Maximum ambient temperature versus supply voltage. (Above curve includes ladder dissipation but not the zener dissipation.)

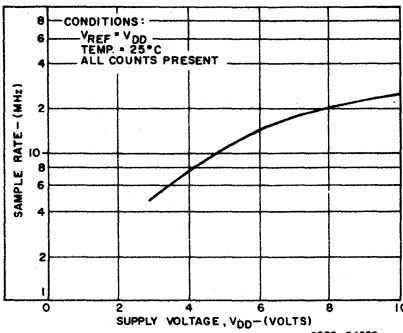


Fig. 5 - Typical maximum sample rate versus supply voltage.

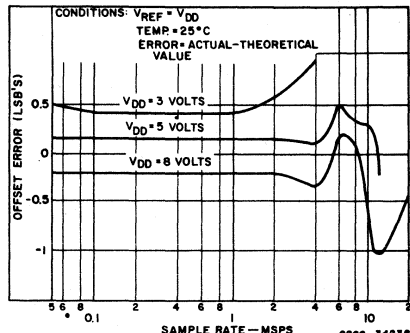


Fig. 6 - Typical offset error versus sample rate as a function of supply voltage. (See literature for offset trim.)

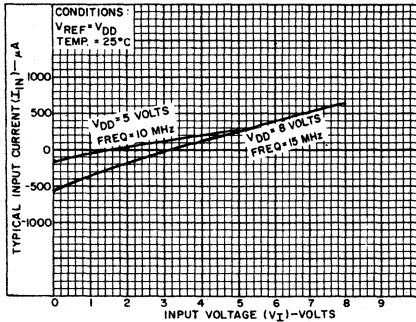


Fig. 7 - Typical input current versus input voltage as a function of supply voltage.

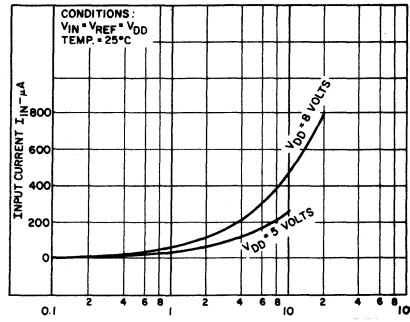


Fig. 8 - Typical input current versus sample rate as a function of supply voltage.

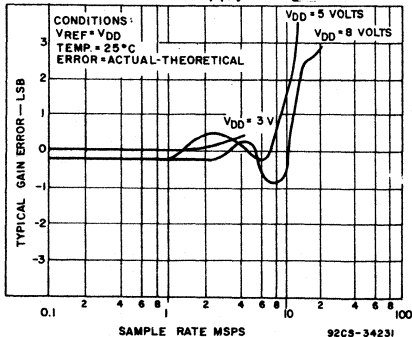


Fig. 9 - Typical gain error versus sample rate as a function of supply voltage. (See literature for gain trim.)

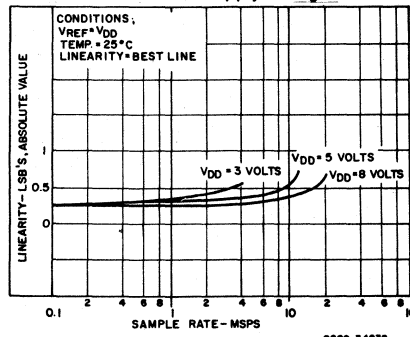


Fig. 10 - Typical linearity versus sample rate as a function of supply voltage.

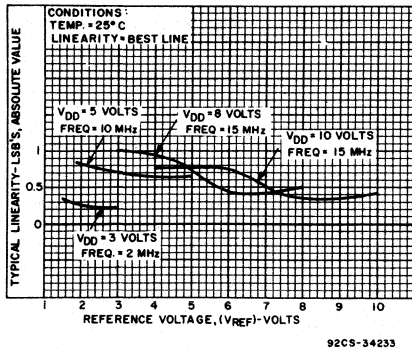


Fig. 11 - Typical linearity versus reference voltage as a function of supply voltage.

Device Operation

A sequential parallel technique is used by the CA3300 converter to obtain its high-speed operation. The sequence consists of the "Auto Balance" phase, $\phi 1$, and the "Sample Unknown" phase $\phi 2$. (Refer to the circuit diagram.) Each conversion takes one clock cycle.* With the phase control (pin 8) low, the "Auto Balance" ($\phi 1$) occurs during the High period of the clock cycle, and the "Sample Unknown" ($\phi 2$) occurs during the low period of the clock cycle.

During the "Auto Balance" phase, a transmission switch is used to connect each of 64 commutating capacitors to their associated ladder reference tap. Those tap voltages will be as follows:

$$V_{\text{tap}}(N) = \left[\frac{V_{\text{REF}}}{64} \times N \right] - \left[\frac{V_{\text{REF}}}{(2 \times 64)} \right] \\ = \frac{V_{\text{REF}}}{128} (2N - 1)$$

Where: $V_{\text{tap}}(n)$ = reference ladder tap voltage at point n.
 V_{REF} = voltage across R⁻ to R⁺
 N = tap number (1 through 64)

The other side of the capacitor is connected to a single stage amplifier whose output is shorted to its input by a switch. This biases the amplifier at its intrinsic trip point, which is approximately, $(V_{\text{DD}} - V_{\text{SS}})/2$. The capacitors now charge to their associated tap voltages, priming the circuit for the next phase.

In the "Sample Unknown" phase, all ladder tap switches are opened, the comparator amplifiers are no longer shorted, and V_{IN} is switch to all 64 capacitors. Since the other end of the capacitor is now looking into an effectively open circuit, any voltage that differs from the previous tap voltage will appear as a voltage shift at the comparator amplifiers. All comparators with tap voltages greater than V_{IN} will drive the comparator outputs to a "low" state, all comparators with tap voltage lower than V_{IN} will drive the comparator outputs to a "high" state.

The status of all these comparator amplifiers are stored at the end of this phase ($\phi 2$), by a secondary latching amplifier stage. Once latched, the status of the 64 comparators is decoded by a 64 to 7 bit decode array and the results are clocked into a storage register at the rising edge of the next $\phi 2$.

A 3-state buffer is used at the output of the 7 storage registers which are controlled by two chip-enable signals. CE1 will independently disable B1 through B6 when it is in a high state. CE2 will independently disable B1 through B6 and the OF buffers when it is in the low state.

To facilitate usage of this device a phase control input is provided which can effectively complement the clock as it enters the chip. Also, an onboard zener is provided for use as a reference voltage.

Continuous Clock Operation

One complete conversion cycle can be traced through the CA3300 via the following steps. (Refer to timing diagram Fig. 2a.) With the phase control in a 'High' state, the rising edge of the clock input will start a "sample" phase. During this entire 'High' state of the clock, the 64 comparators will track the input voltage and the 64 latches will track the comparator outputs. At the falling edge of the clock, all 64 comparator outputs are captured by the 64 latches. This ends the "sample" phase and starts the "auto balance" phase for the comparators. During this 'Low' state of the clock the output of the latches propagates through the decode array and a 7-bit code appears at the D inputs of the output registers. On the next rising edge of the clock, this 7-bit code is shifted into the output registers and appears with time delay t_d as valid data at the output of the 3-state drivers. This also marks the start of a new "sample" phase, thereby repeating the conversion process for this next cycle.

Pulse Mode Operation

For sampling high-speed nonrecurrent or transient data, the converter may be operated in a pulse mode in one of two ways. The fastest method is to keep the converter in the Sample Unknown phase, $\phi 2$, during the standby state. The device can now be pulsed through the Auto Balance phase with as little as 33 ns. The analog value is captured on the leading edge of $\phi 1$ and is transferred into the output registers on the trailing edge of $\phi 1$. We are now back in the standby state, $\phi 2$, and another conversion can be started within 33 ns, but not later than 10 μs due to the eventual droop of the commutating capacitors. Another advantage of this method is that it has the potential of having the lowest power drain. The larger the time ratio between $\phi 2$ and $\phi 1$, the lower the power consumption. (See timing diagram Fig. 2b.)

The second method uses the Auto Balance phase, $\phi 1$, as the standby state. In this state the converter can stay indefinitely waiting to start a conversion. A conversion is performed by strobing the clock input with two $\phi 2$ pulses. The first pulse starts a Sample Unknown phase and captures the analog value in the comparator latches on the trailing edge. A second $\phi 2$ pulse is needed to transfer the data into the output registers. This occurs on the leading edge of the second pulse. The conversion now takes place in 67 ns, but the repetition rate may be as slow as desired. The disadvantage to this method is the higher device dissipation due to the low ratio of $\phi 2$ to $\phi 1$. (See timing diagram Fig. 2c.)

Increased Accuracy

In most cases the accuracy of the CA3300 should be

*This device requires only a single phase clock. The terminology of $\phi 1$ and $\phi 2$ refers to the High and Low periods of the same clock.

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sufficient without any adjustments. In applications where accuracy is of utmost importance, three adjustments can be made to obtain better accuracy; i.e., offset trim, gain trim, and midpoint trim.

Offset Trim

In general offset correction can be done in the preamp circuitry by introducing a DC shift to V_{IN} or by the offset trim of the op-amp. When this is not possible the R^- (pin 10) input can be adjusted to produce an offset trim. The theoretical input voltage to produce the first transition is $\frac{1}{2}$ LSB. The equation is as follows:

$$V_{IN} \text{ (0 to 1 transition)} = \frac{1}{2} \text{ LSB} = \frac{1}{2}(V_{REF}/64) \\ = V_{REF}/128$$

If V_{IN} for the first transition is less than the theoretical, then a single-turn 50-ohm pot connected between R^- and ground will accomplish the adjustment. Set V_{IN} to $\frac{1}{2}$ LSB and trim the pot until the 0 to 1 transition occurs.

If V_{IN} for the first transition is greater than the theoretical, then the 50-ohm pot should be connected between R^- and a negative voltage of about 2 LSB's. The trim procedure is as stated previously.

Gain Trim

In general the gain trim can also be done in the preamp circuitry by introducing a gain adjustment for the op-amp. When this is not possible, then a gain adjustment circuit should be made to adjust the reference voltage. To perform this trim, V_{IN} should be set to the 63 to overflow transition. That voltage is $\frac{1}{2}$ LSB less than V_{REF} and is calculated as follows:

$$V_{IN} \text{ (63 to 64 transition)} = V_{REF} - V_{REF}/128 \\ = V_{REF} (127/128)$$

To perform the gain trim, first do the offset trim and then apply the required V_{IN} for the 63 to overflow transition. Now adjust V_{REF} until that transition occurs on the outputs.

Midpoint Trim

The reference center (RC), pin 16, is available to the user as the approximate midpoint of the resistor ladder. The actual

count that is brought out is count 33. To trim the midpoint the offset and gain trims should be done first. The theoretical transition from count 32 to 33 occurs at $32\frac{1}{2}$ LSB's. That voltage is as follows:

$$V_{IN} \text{ (32 to 33 transition)} = 32.5 (V_{REF}/64)$$

An adjustable voltage follower can be connected to the RC pin or a 2K pot can be connected between R^+ and R^- with the wiper connected to RC. Set V_{IN} to the 32 to 33 transition voltage, then adjust the voltage follower or the pot until the transition occurs on the output bits.

The Reference Center point can also be used to create some unique transfer functions. For example, if R^- is grounded, RC is connected to 3.25 volts, and R^+ is connected to 4.8 volts then the lower order counts, 1 through 33, will have an LSB value of 100 mV while the upper order counts, 34 through Overflow, will have an LSB value of 50 mV. This effectively provides twice the sensitivity in the upper counts as compared to the lower counts.

7-Bit Resolution

To obtain 7-bit resolution, two CA3300s can be wired together. Necessary ingredients include an open-ended ladder network, an overflow indicator, three-state outputs, and chip-enabler controls—all of which are available on the CA3300.

The first step for connecting a 7-bit circuit is to totem-pole the ladder networks, as illustrated in Fig. 13. Since the absolute resistance value of each ladder may vary, external trim of the mid-reference voltage may be required.

The overflow output of the lower device now becomes the seventh bit. When it goes high, all counts must come from the upper device. When it goes low, all counts must come from the lower device. This is done simply by connecting the lower overflow signal to the $\overline{CE1}$ control of the lower a-d converter and the CE2 control of the upper a-d converter. The three-state outputs of the two devices (bits 1 through 6) are now connected in parallel to complete the circuitry. The complete circuit for a 7-bit a-d converter is shown in Fig. 14.

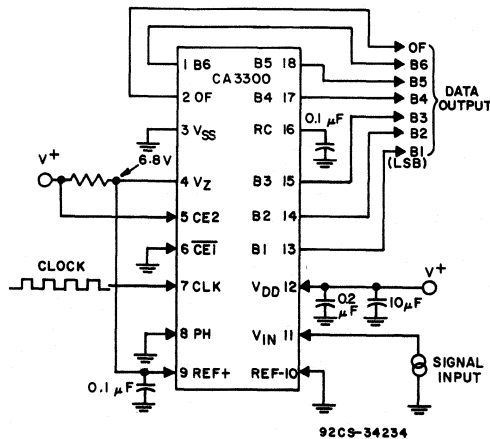
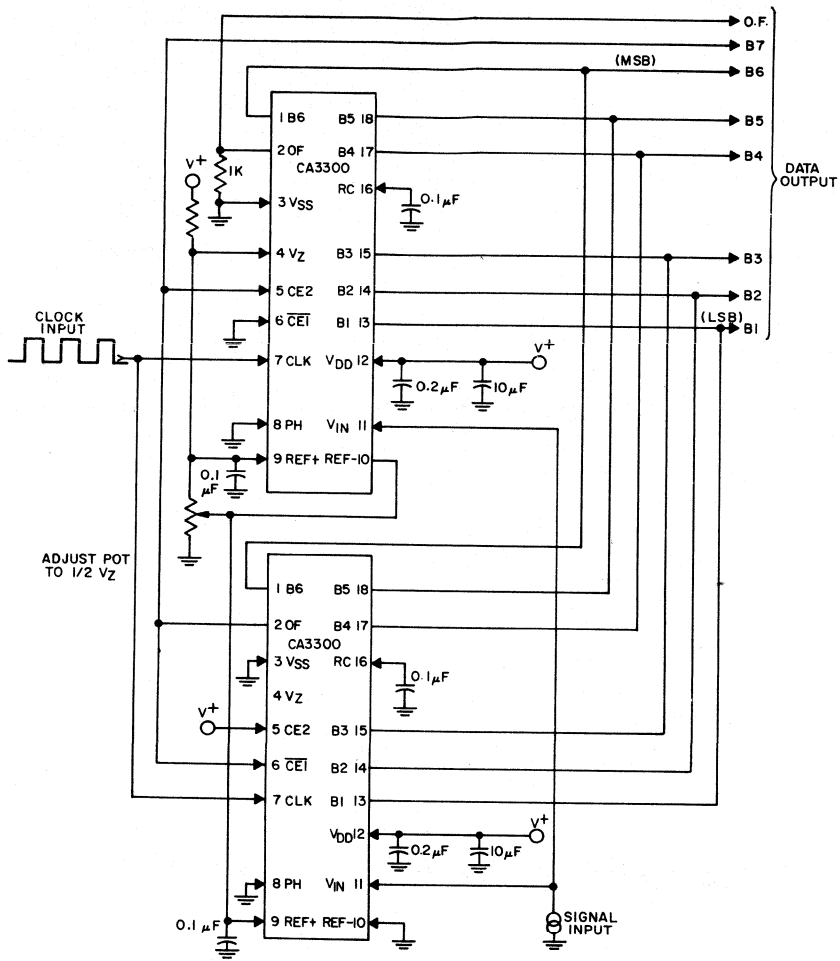


Fig. 12 - Typical CA3300 6-bit configuration 15-MHz sampling rate.



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Fig. 13 - Typical CA3300 7-bit resolution configuration 15-MHz sampling rate.

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CA3300

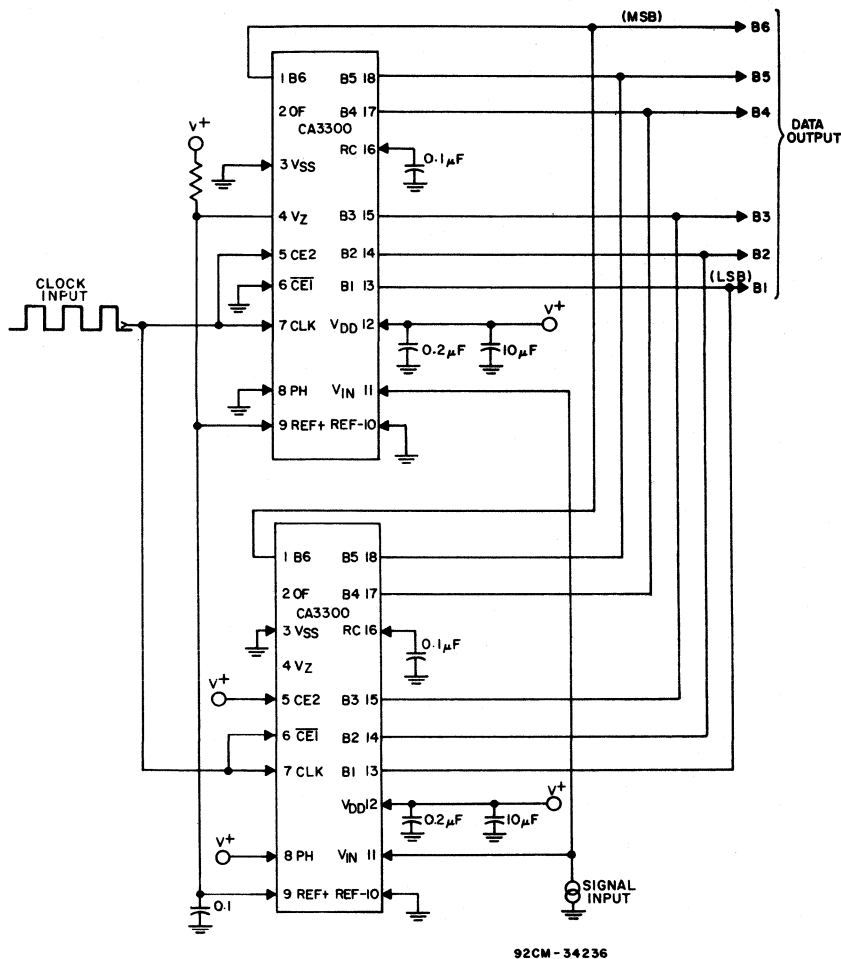


Fig. 14 - Typical CA3300 6-bit resolution configuration 30-MHz sampling rate.

8-Bit to 12-Bit Conversion Techniques

To obtain 8 to 12-bit resolution and accuracy, use a feed-forward conversion technique. Two a-d converters will be needed to convert up to 11 bits; three a-d converters to convert 12 bits. The high speed of the CA3300 allows 12-bit conversions in the 500 to 900-ns range.

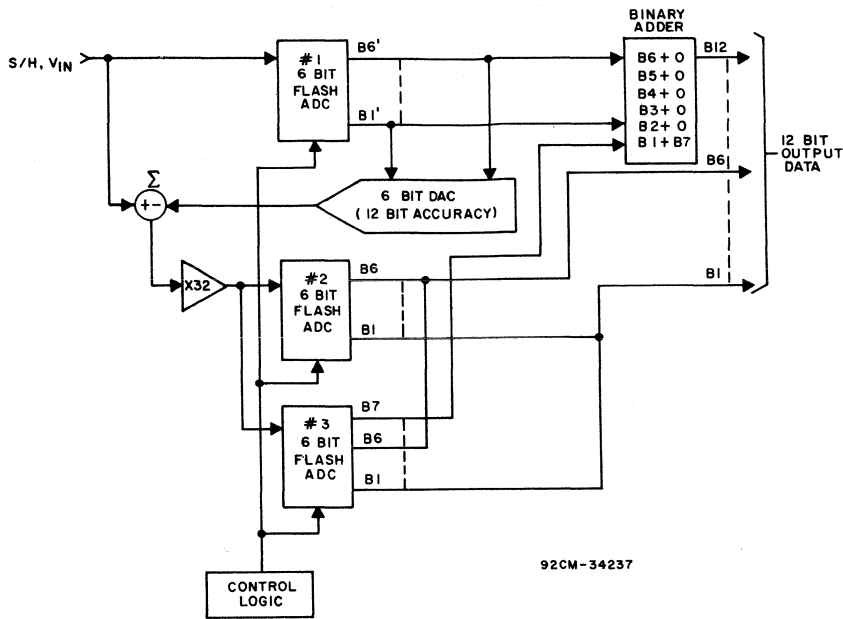
The circuit diagram of a high-speed 12-bit a-d converter is shown in Fig. 15. In the feed-forward conversion method two sequential conversions are made. Converter A first does a coarse conversion to 6 bits. The output is applied to a 6-bit d-a converter whose accuracy level is good to 12 bits. The d-a converter output is then subtracted from the input voltage, multiplied by 32, and then converted by a second flash a-d converter, which is connected in a 7-bit

configuration. The answers from the first and second conversions are added together with bit 1 of the first conversion overlapping bit 7 of the second conversion.

When using this method, take care that:

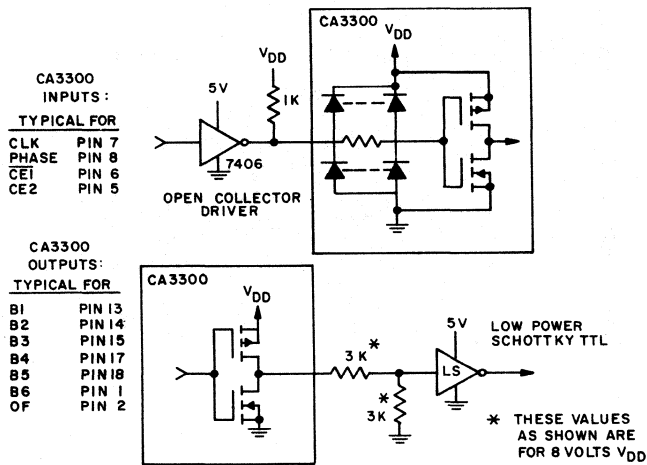
- The linearity of the first converter is better than 1/2 LSB.
- An offset bias of 1 LSB (1/64) is subtracted from the first conversion since the second converter is unipolar.
- The d-a converter and its reference are accurate to the total number of bits desired for the final conversion (the a-d converter need only be accurate to 6 bits).

The first converter can be offset-biased by adding a 20-Ω resistor at the bottom of the ladder and increasing the reference voltage by 1 LSB. If a 6.40-voltage reference is used in the system, for example, then the first CA3300 will require a 6.5-V reference.



92CM-34237

Fig. 15 - Typical CA3300 800-nanosecond 12-bit ADC system.



92CM-34229

Fig. 16 - TTL interface circuit for $V_{DD} > 5.5$ volts.

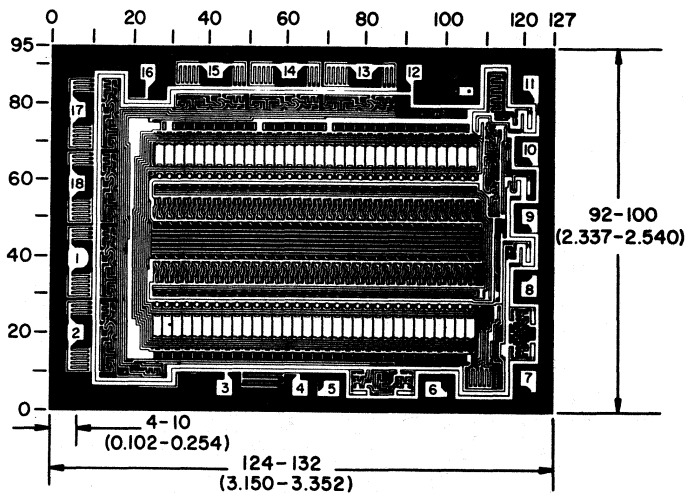
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OUTPUT CODE TABLE

CODE DESCRIPTION	INPUT VOLTAGE*				BINARY OUTPUT CODE							DECIMAL COUNT
	VREF 7.68 (VOLTS)	VREF 6.40 (VOLTS)	VREF 5.12 (VOLTS)	VREF 3.20 (VOLTS)	(LSB)							
					0.F	B6	B5	B4	B3	B2	B1	
ZERO	0.00	0.00	0.00	0.00	0	0	0	0	0	0	0	0
1 LSB	0.12	0.10	0.08	0.05	0	0	0	0	0	0	1	1
2 LSB	0.24	0.20	0.16	0.10	0	0	0	0	0	1	0	2
.
.
1/2 Full Scale - 1 LSB	3.72	3.10	2.48	1.55	0	0	1	1	1	1	1	31
1/2 Full Scale	3.84	3.20	2.56	1.60	0	1	0	0	0	0	0	32
1/2 Full Scale +1 LSB	3.96	3.30	2.64	1.65	0	1	0	0	0	0	1	33
.
.
Full Scale - 1 LSB	7.44	6.20	4.96	3.10	0	1	1	1	1	1	0	62
Full Scale	7.56	6.30	5.04	3.15	0	1	1	1	1	1	1	63
Overflow	7.68	6.40	5.12	3.20	1	1	1	1	1	1	1	127

*THE VOLTAGES LISTED BELOW ARE THE IDEAL CENTERS OF EACH OUTPUT CODE SHOWN AS A FUNCTION OF ITS ASSOCIATED REFERENCE VOLTAGE.



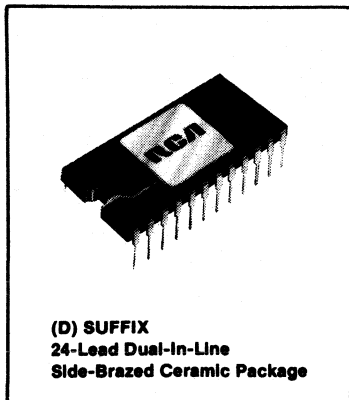
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Dimensions and pad layout for CA3300H.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

The photographs and dimensions of each COS/MOS chip represent a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

CMOS Video Speed 8-Bit Flash Analog-to-Digital Converter



(D) SUFFIX
24-Lead Dual-In-Line
Side-Brazed Ceramic Package

For Use in Low-Power Consumption,
High-Speed Digitization Applications

Features:

- CMOS low power with SOS speed
- Parallel conversion technique
- 15-MHz sampling rate (66-ns conversion time)
- 8-bit latched 3-state output with overflow bit
- $\pm 1/2$ LSB accuracy (typ.)
- Single supply voltage (4 to 8 V)
- 2 units in series allow 9-bit output
- 2 units in parallel allow 30-MHz sampling rate

The RCA CA3308* is a CMOS 240-mW parallel (FLASH) analog-to-digital converter designed for applications demanding both low-power consumption and high-speed digitization.

The CA3308 operates over a wide full-scale input-voltage range of 4 volts up to 8 volts with maximum power consumptions as low as 240 mW, depending upon the clock frequency selected. When operated from a 5-volt supply at a clock frequency of 15 MHz, the power consumption of the CA3308 is typically 240 mW.

The intrinsic high conversion rate makes the CA3308 ideally suited for digitizing high-speed signals. The overflow bit makes possible the connection of two or more CA3308s in series to increase the resolution of the conversion system. A series connection of two CA3308s may be used to produce a 9-bit high-speed converter. Operation of two CA3308s in parallel doubles the conversion speed (i.e., increases the sampling rate from 15 to 30 MHz). CA3308s may be combined with a high-speed 8-bit D/A converter, a binary adder, control logic, and an op amp to form a very high-speed 15-bit A/D converter.

256 paralleled auto-balanced voltage comparators measure the input voltage with respect to a known reference to produce the parallel-bit outputs in the CA3308.

255 comparators are required to quantize all input voltage levels in this 8-bit converter, and the additional comparator is required for the overflow bit.

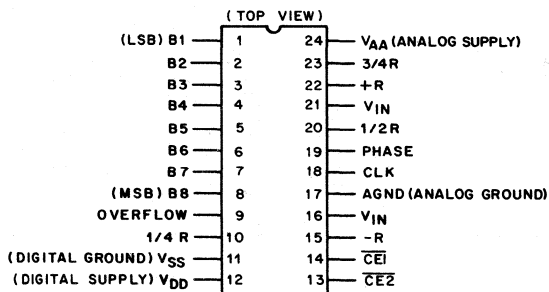
The voltage supply for analog circuitry is termed V_{AA} and AGND. The voltage supply for digital circuitry is termed V_{DD} and V_{SS} .

The CA3308 type is available in a 24-lead dual-in-line ceramic package (D suffix).

* Formerly Developmental Type No. TA11279.

Applications:

- The CA3308 is especially suited for high-speed conversion applications where low power is also important
- TV video digitizing (industrial/security/broadcast)
- High-speed A/D conversion
- Ultrasound signature analysis
- Transient signal analysis
- High-energy physics research
- High-speed oscilloscope storage/display
- General-purpose hybrid ADCs
- Optical character recognition
- Radar pulse analysis
- Motion signature analysis
- μ P data acquisition systems



92CS-34789

TERMINAL ASSIGNMENT

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MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE RANGE (V_{DD} AND V_{AA})	
(VOLTAGE REFERENCED TO V_{SS} TERMINAL) -0.5 to +8 V
INPUT VOLTAGE RANGE	
ALL INPUTS -0.5 to V_{DD} +0.5 V
DC INPUT CURRENT	
CLK, PH, CE1, CE2, V_{IN} ± 10 mA
POWER DISSIPATION PER PACKAGE (P_D)	
FOR $T_A = -40$ to 55°C 315 mW
FOR $T_A = 55^\circ\text{C}$ to 85°C Derate linearly at 3.3 mW/ $^\circ\text{C}$
TEMPERATURE RANGE	
OPERATING -40 to +85 $^\circ\text{C}$
STORAGE -65 to +150 $^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING)	
AT DISTANCE $1/16 \pm 1/32$ in. (1.59 ± 0.79 mm) FROM CASE FOR 10 s MAX. +265 $^\circ\text{C}$

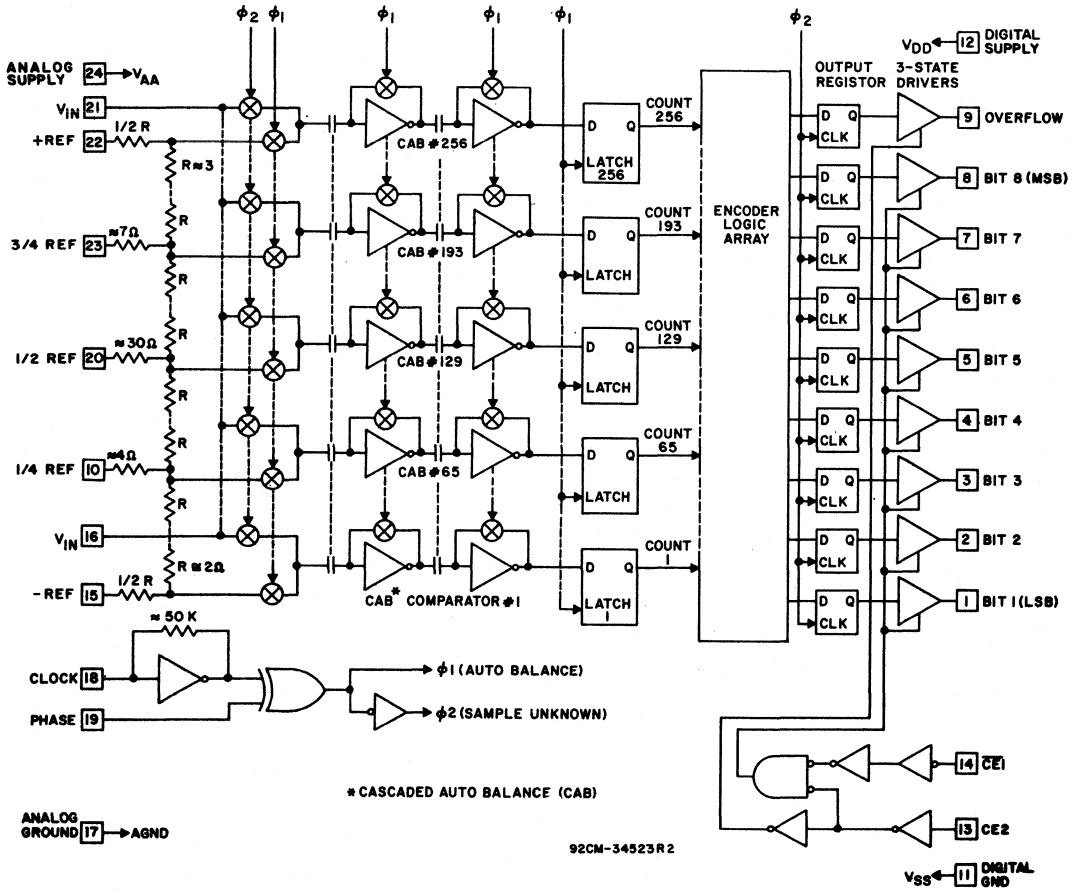


Fig. 1-Block diagram for the CA3308.

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	TEST CONDITIONS $V_{AA} = V_{DD}$	LIMITS			UNITS
		MIN.	TYP.	MAX.	
Resolution		—	—	8	Bits
Linearity Error	$V_{DD}=5\text{ V}$, $V_{REF}=6.4\text{ V}$ $\text{CLK}=15\text{ MHz}$, gain adjusted	—	—	± 1	(CA3308D)
Differential Linearity Error	$V_{DD}=5\text{ V}$, $V_{REF}=6.4\text{ V}$ $\text{CLK}=15\text{ MHz}$	—	—	± 1	(CA3308D)
Quantizing Error		$-\frac{1}{2}$	—	$\frac{1}{2}$	LSB
Analog Input: Full Scale Range	$V_{DD}=5\text{ V}$ $\text{CLK}=15\text{ MHz}$	4	—	8	V
Input Capacitance		—	50	—	pF
Input Current	$V_{IN}=6.4\text{ V}$	—	1000	2000	μA
Maximum Conversion Speed	$V_{DD}=5\text{ V}$	15 M	17 M	—	SPS
Device Current (Excludes I_{REF})	$V_{DD}=5\text{ V}$ ($\text{CLK}=15\text{ MHz}$)	—	30	—	mA
Ladder Impedance		300	600	900	Ω
Digital Inputs: Low Voltage		—	—	1.5	V
High Voltage	$V_{DD}=5\text{ V}$	3.5	—	—	V
Input Current (Except Pin 18)		—	± 1	—	μA
Digital Outputs: Output Low (Sink) Current	$V_{DD}=5\text{ V}$, $V_O=0.4\text{ V}$	3.2	10	—	mA
Output High (Source) Current	$V_{DD}=5\text{ V}$, $V_O=4.6\text{ V}$	1.6	-6	—	mA
Digital Output Delay, t_d	$V_{DD}=5\text{ V}$	—	25	—	ns

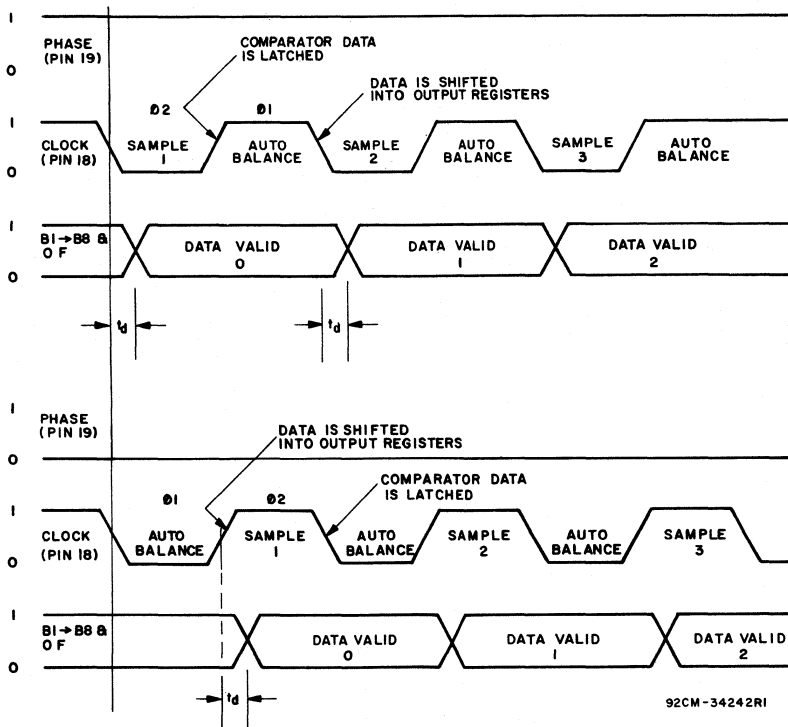
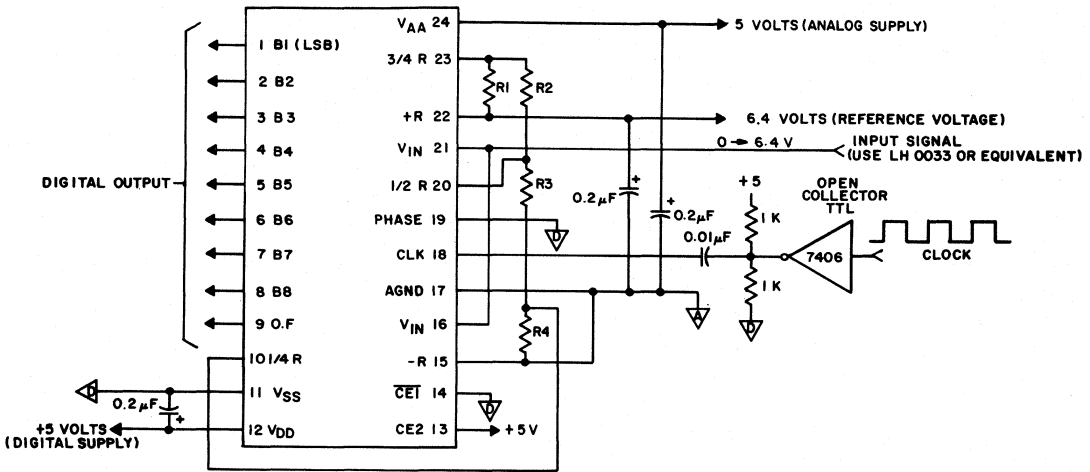


Fig. 2—Timing diagram for the CA3308.

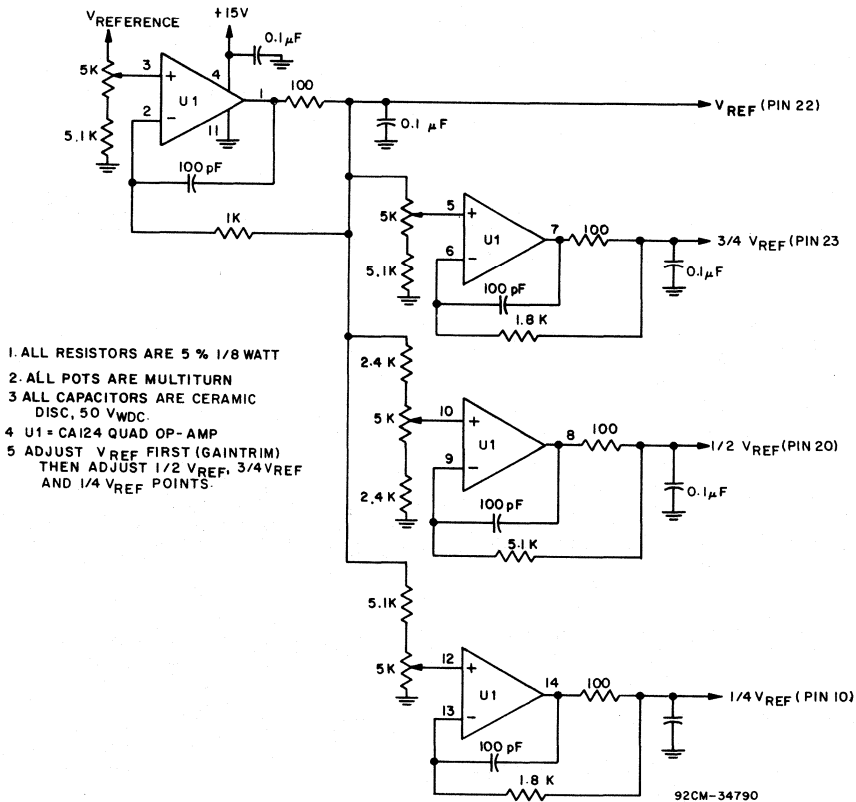
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CA3308



- NOTES
1. R1—R4=100Ω, 0.1% 1/8 WATT (DELETE WHEN USING REFERENCE DRIVER CIRCUIT)
 2. A GROUND AND D GROUND MUST BE CONNECTED TO EACH OTHER NEAR THE CHIP.
 3. V_{AA}+6V WILL IMPROVE LINEARITY
- 92CM-34618R2

Fig. 3—Typical circuit configuration for the CA3308.
(15-MHz sampling rate)



1. ALL RESISTORS ARE 5% 1/8 WATT
2. ALL POTS ARE MULTITURN
3. ALL CAPACITORS ARE CERAMIC DISC, 50 V_{WDC}.
4. U1 = CA124 QUAD OP-AMP
5. ADJUST V_{REF} FIRST (GAIN TRIM) THEN ADJUST 1/2 V_{REF}, 3/4 V_{REF} AND 1/4 V_{REF} POINTS.

Fig. 4—Reference driver circuit.
(Use for maximum linearity)

Device Operation

A sequential parallel technique is used by the CA3308 converter to obtain its high-speed operation. The sequence consists of the "Auto Balance" phase, ϕ_1 , and the "Sample Unknown" phase ϕ_2 . (Refer to the circuit diagram.) Each conversion takes one clock cycle.* With the phase control (pin 8) high, the "Auto Balance" (ϕ_1) occurs during the High period of the clock cycle, and the "Sample Unknown" (ϕ_2) occurs during the low period of the clock cycle.

During the "Auto Balance" phase, a transmission switch is used to connect each of the first set of 256 commutating capacitors to their associated ladder reference tap. Those tap voltages will be as follows:

$$V_{\text{tap}}(N) = [(N/256) V_{\text{REF}} - (1/512) V_{\text{REF}}] \\ = [2N - 1/512] V_{\text{REF}}$$

Where:

$V_{\text{tap}}(n)$ = reference ladder tap voltage at point n.

V_{REF} = voltage across $-REF$ to $+REF$

N = tap number (1 through 256)

The other side of these capacitors are connected to single stage amplifiers whose outputs are shorted to their inputs by switches. This balances the amplifiers at their intrinsic trip points, which is approximately, $V_{\text{DD}} - V_{\text{SS}}/2$. The first set of capacitors now charge to their associated tap voltages.

At the same time a second set of commutating capacitors and amplifiers are also auto-balanced. The balancing of the second stage amplifier at its intrinsic trip point removes any tracking differences between the first and second amplifier stages. The cascaded auto-balance (CAB) technique, used here, increases comparator sensitivity and temperature tracking.

In the "Sample Unknown" phase, all ladder tap switches and comparator shorting switches are opened. At the same time V_{IN} is switched to the first set of commutating

*This device requires only a single phase clock. The terminology of ϕ_1 and ϕ_2 refers to the High and Low periods of the same clock.

capacitors. Since the other end of the capacitors are now looking into an effectively open circuit, any input voltage that differs from the previous tap voltage will appear as a voltage shift at the comparator amplifiers. All comparators that had tap voltages greater than V_{IN} will go to a "low" state at their outputs. All comparators that had tap voltages lower than V_{IN} will go to a "high" state.

The status of all these comparator amplifiers are ac coupled through the second stage comparator and stored at the end of this phase (ϕ_2), by a latching amplifier stage. Once latched, the status of the comparators are decoded by a 256 to 9-bit decode array and the results are clocked into a storage register at the rising edge of the next ϕ_2 .

A 3-state buffer is used at the output of the 9 storage registers which are controlled by two chip-enable signals. CE1 will independently disable B1 through B8 when it is in a high state. CE2 will independently disable B1 through B8 and the OF buffers when it is in the low state.

To facilitate usage of this device a phase control input is provided which can effectively complement the clock as it enters the chip.

Continuous Clock Operation

One complete conversion cycle can be traced through the CA3308 via the following steps. (Refer to timing diagram No. 1.) With the phase control in a "low" state, the rising edge of the clock input will start a "sample" phase. During this entire "high" state of the clock, the comparators will track the input voltage and the latches will track the comparator outputs. At the falling edge of the clock, all 256 comparator outputs are captured by the 256 latches. This ends the "sample" phase and starts the "auto balance" phase for the comparators. During this "low" state of the clock the output of the latches propagates through the decode array and a 9-bit code appears at the D inputs of the output registers. On the next rising edge of the clock, this 9-bit code is shifted into the output registers and appears with time delay t_{d} as valid data at the output of the 3-state drivers. This also marks the start of a new "sample" phase, thereby repeating the conversion process for this next cycle.

OPERATING AND HANDLING CONSIDERATIONS**1. Handling**

All inputs and outputs of RCA CMOS devices have a network for electrostatic protection during handling. Recommended handling practices for CMOS devices are described in ICAN-6525 "Guide to Better Handling and Operation of CMOS Integrated Circuits."

2. Operating**Operating Voltage**

During operation near the maximum supply voltage limit, care should be taken to avoid or suppress power supply turn-on and turn-off transients, power supply ripple, or ground noise; any of these conditions must not cause $V_{\text{DD}} - V_{\text{SS}}$ to exceed the absolute maximum rating.

Input Signals

To prevent damage to the input protection circuit, input signals should never be greater than V_{DD} nor less than V_{SS} . Input currents must not exceed 10 mA even when the power supply is off.

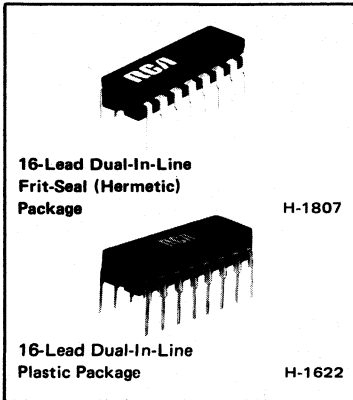
Unused Inputs

A connection must be provided at every input terminal. All unused input terminals must be connected to either V_{DD} or V_{SS} , whichever is appropriate.

Output Short Circuits

Shorting of outputs to V_{DD} or V_{SS} may damage CMOS devices by exceeding the maximum device dissipation.

CA3081, CA3082 Types



General-Purpose High-Current N-P-N Transistor Arrays

CA3081 — Common-Emitter Array

CA3082 — Common-Collector Array

Directly Drive 7-Segment Incandescent Displays and Light-Emitting-Diode (LED) Displays

Features:

- 7 transistors permit a wide range of applications in either a common-emitter [CA3081] or common-collector [CA3082] configuration
- High I_C : 100 mA max.
- Low $V_{CE\ sat}$ (at 50 mA): 0.4 V typ.

Applications:

- Drivers for:
 - Incandescent display devices [e.g. RCA NUMITRON DR2000 Series and lamps]
 - LED [e.g. RCA-40736R GaAs High-Efficiency Emitting Diode]
 - Relay control
 - Thyristor firing

RCA-CA3081 and CA3082 consist of seven high-current (to 100 mA) silicon n-p-n transistors on a common monolithic substrate. The CA3081 is connected in a common-emitter configuration and the CA3082 is connected in a common-collector configuration.

The CA3081 and CA3082 are capable of directly driving seven-segment displays, such as the RCA NUMITRON devices (DR2000 and DR2010), and light-emitting diode (LED) displays. These types are also well-suited for a variety of

other drive applications, including relay control and thyristor firing.

The CA3081 and CA3082 are supplied in a 16-lead dual-in-line plastic package, and the CA3081F and CA3082F in a 16-lead dual-in-line frit-seal ceramic package, which includes a separate substrate connection for maximum flexibility in circuit design. Both types are also available in chip form.

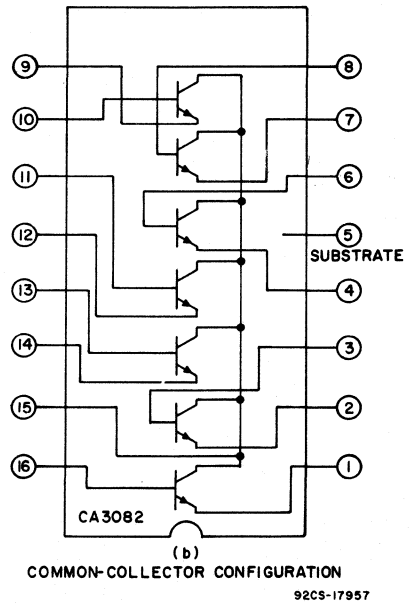
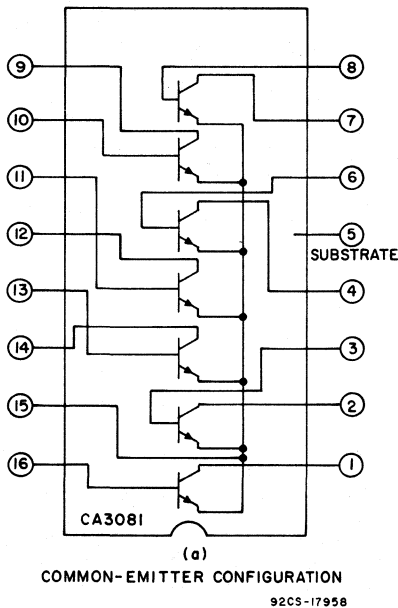


Fig. 1 — Functional diagrams of types CA3081 and CA3082.

Data Conversion Circuits CA3081, CA3082 Types

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

Power Dissipation:

Any one transistor	500	mW
Total package	750	mW
Above 55°C	Derate linearly 6.67	$\text{mW}/^\circ\text{C}$

Ambient Temperature Range:

Operating	-55 to $+125$	$^\circ\text{C}$
Storage	-65 to $+150$	$^\circ\text{C}$

Lead Temperature (During Soldering):

At distance $1/16'' \pm 1/32''$ ($1.59 \text{ mm} \pm 0.79 \text{ mm}$)		
from case for 10 seconds max.	265	$^\circ\text{C}$

The following ratings apply for each transistor in the device:

Collector-to-Emitter Voltage (V_{CEO})	16	V
Collector-to-Base Voltage (V_{CBO})	20	V
Collector-to-Substrate Voltage (V_{C10}) [■]	20	V
Emitter-to-Base Voltage (V_{EBO})	5	V
Collector Current (I_{C})	100	mA
Base Current (I_{B})	20	mA

* The collector of each transistor of the CA3081 and CA3082 is isolated from the substrate by an integral diode. The substrate must be connected to a voltage which is more negative than any collector voltage in order to maintain isolation between transistors and

provide normal transistor action. To avoid undesired coupling between transistors, the substrate terminal (5) should be maintained at either DC or signal (AC) ground. A suitable bypass capacitor can be used to establish a signal ground.

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$ For Equipment Design

CHARACTERISTIC	SYMBOL	TEST CONDITIONS		LIMITS			UNITS
			Typ. Char. Curve Fig. No.	Min.	Typ.	Max.	
Collector-to-Base Breakdown Voltage	$V_{\text{(BR)CES}}$	$I_{\text{C}} = 500 \mu\text{A}, I_{\text{E}} = 0$	—	20	60	—	V
Collector-to-Substrate Breakdown Voltage	$V_{\text{(BR)C10}}$	$I_{\text{C1}} = 500 \mu\text{A}, I_{\text{E}} = 0, I_{\text{B}} = 0$	—	20	60	—	V
Collector-to-Emitter Breakdown Voltage	$V_{\text{(BR)CEO}}$	$I_{\text{C}} = 1 \text{ mA}, I_{\text{B}} = 0$	—	16	24	—	V
Emitter-to-Base Breakdown Voltage	$V_{\text{(BR)EBO}}$	$I_{\text{C}} = 500 \mu\text{A}$	—	5	6.9	—	V
DC Forward-Current Transfer Ratio	h_{FE}	$V_{\text{CE}} = 0.5 \text{ V}, I_{\text{C}} = 30 \text{ mA}$	—	30	68	—	
		$V_{\text{CE}} = 0.8 \text{ V}, I_{\text{C}} = 50 \text{ mA}$	—	40	70	—	
Base-to-Emitter Saturation Voltage	$V_{\text{BE sat}}$	$I_{\text{C}} = 30 \text{ mA}, I_{\text{B}} = 1 \text{ mA}$	3	—	0.87	1.0	V
Collector-to-Emitter Saturation Voltage: CA3081, CA3082	$V_{\text{CE sat}}$	$I_{\text{C}} = 30 \text{ mA}, I_{\text{B}} = 1 \text{ mA}$	—	—	0.27	0.5	V
		CA3081 $I_{\text{C}} = 50 \text{ mA}, I_{\text{B}} = 5 \text{ mA}$	4	—	0.4	0.7	
		CA3082 $I_{\text{C}} = 50 \text{ mA}, I_{\text{B}} = 5 \text{ mA}$	4	—	0.4	0.8	
Collector-Cutoff-Current	I_{CEO}	$V_{\text{CE}} = 10 \text{ V}, I_{\text{B}} = 0$	—	—	—	10	μA
Collector-Cutoff Current	I_{CBO}	$V_{\text{CB}} = 10 \text{ V}, I_{\text{E}} = 0$	—	—	—	1	μA

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CA3081, CA3082 Types

TYPICAL STATIC CHARACTERISTICS FOR EACH TRANSISTOR OF TYPES CA3081 AND CA3082

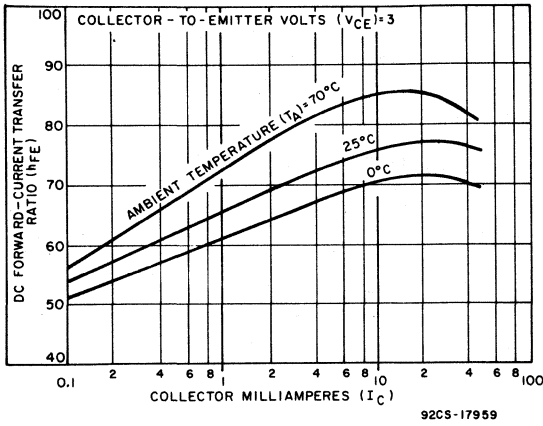


Fig.2— h_{FE} vs. I_C

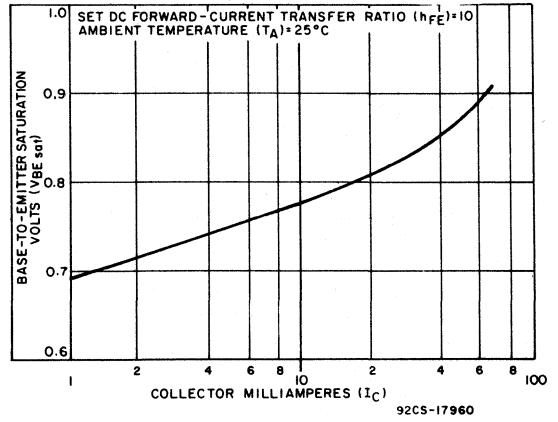


Fig.3— $V_{BE sat}$ vs. I_C

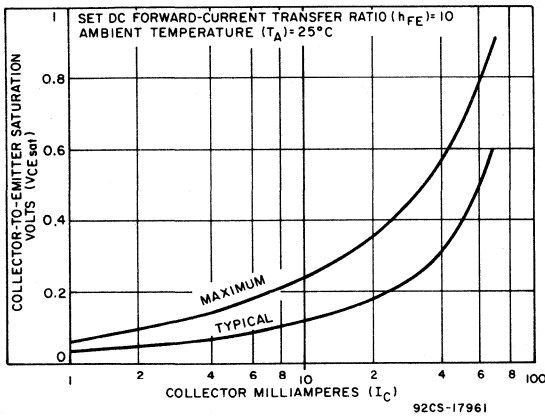


Fig.4— $V_{CE sat}$ vs. I_C at $T_A = 25^\circ C$.

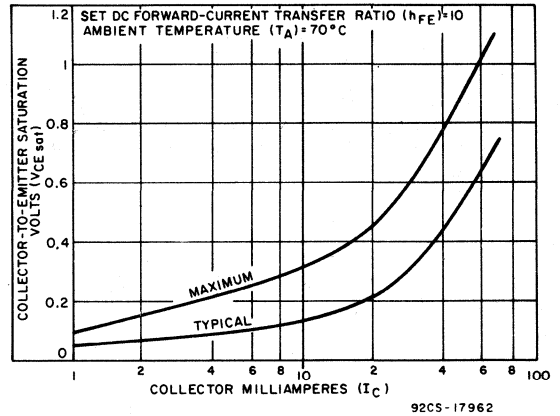


Fig.5— $V_{CE sat}$ vs. I_C at $T_A = 70^\circ C$.

TYPICAL READ-OUT DRIVER APPLICATIONS

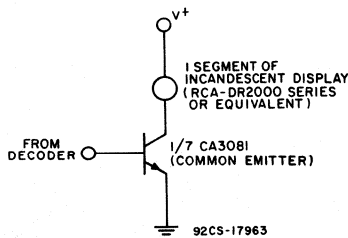


Fig.6—Schematic diagram showing one transistor of the CA3081 driving one segment of an incandescent display.

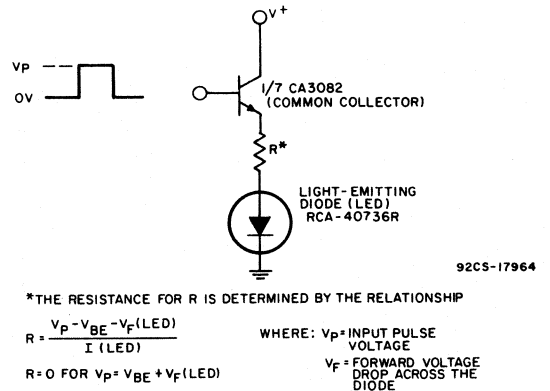
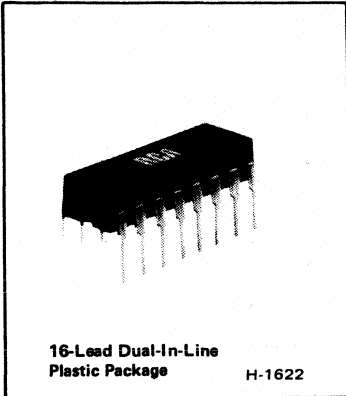


Fig.7—Schematic diagram showing one transistor of the CA3082 driving a light-emitting diode (LED).



BCD-to-Seven-Segment Decoder/Driver

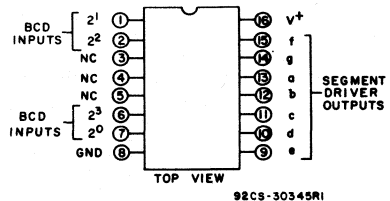
Features:

- TTL-compatible input logic levels
- 25-mA [typ.] constant-current segment outputs
- Eliminates need for output current-limiting resistors
- Pin compatible with other industry standard decoders
- Low standby power dissipation - 18 mW (typ.)

The RCA-CA3161E is a monolithic integrated circuit that performs the BCD-to-seven-segment decoding function and features constant-current segment drivers. When used with the CA3162E A/D Converter* the CA3161E provides a complete digital readout system with a minimum number of external parts.

The CA3161 is supplied in the 16-lead dual-in-line plastic package (E suffix). The CA3161 is also available in chip form (H suffix).

*The CA3162E is described in RCA data bulletin File No. 1080.



**TERMINAL ASSIGNMENT
CA3161E**

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE (between terminals 1 and 10)	+7 V
INPUT VOLTAGE (terminals 1, 2, 6, 7)	+5.5 V
OUTPUT VOLTAGE:	
Output "Off"	+7 V
Output "On" (See note 1)	+10 V
DEVICE DISSIPATION:	
Up to $T_A = +55^\circ\text{C}$	1 W
Above $T_A = +55^\circ\text{C}$	derate linearly at 10.5 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:	
Operating	0 to $+75^\circ\text{C}$
Storage	-65 to $+150^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10 seconds max.	$+265^\circ\text{C}$

NOTE 1: This is the maximum output voltage for any single output. The output voltage must be consistent with the maximum dissipation and derating curve for worst-case conditions. Example: All segments "on", 100% duty cycle.

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CA3161E

TRUTH TABLE

BINARY STATE	INPUTS				OUTPUTS							DISPLAY	
	2 ³	2 ²	2 ¹	2 ⁰	a	b	c	d	e	f	g		
0	L	L	L	L	L	L	L	L	L	L	L	H	0
1	L	L	L	H	H	L	L	H	H	H	H	H	1
2	L	L	H	L	L	L	H	L	L	H	L	L	2
3	L	L	H	H	L	L	L	L	H	H	L	L	3
4	L	H	L	L	H	L	L	H	H	L	L	L	4
5	L	H	L	H	L	H	L	L	H	L	L	L	5
6	L	H	H	L	L	H	L	L	L	L	L	L	6
7	L	H	H	H	L	L	L	H	H	H	H	H	7
8	H	L	L	L	L	L	L	L	L	L	L	L	8
9	H	L	L	H	L	L	L	L	H	L	L	L	9
10	H	L	H	L	H	H	H	H	H	H	L	L	—
11	H	L	H	H	L	H	H	L	L	L	L	L	E
12	H	H	L	L	H	L	L	H	L	L	L	L	H
13	H	H	L	H	H	H	H	L	L	L	H	L	L
14	H	H	H	L	L	L	H	H	L	L	L	L	P
15	H	H	H	H	H	H	H	H	H	H	H	H	BLANK

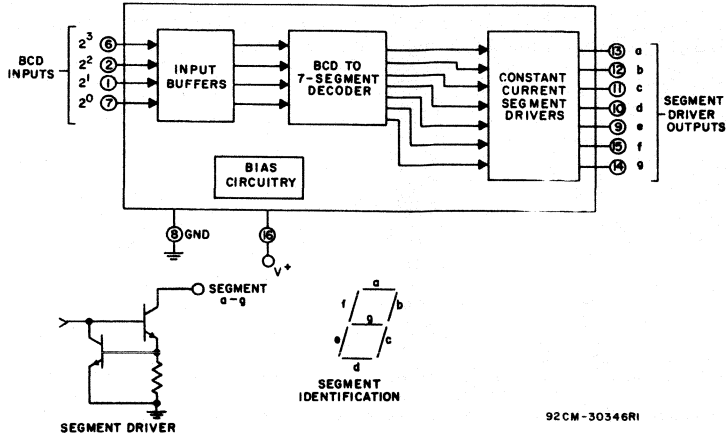


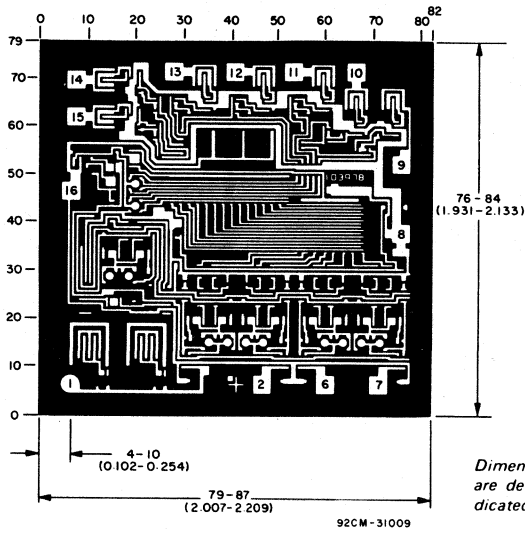
Fig. 1-Functional block diagram of the CA3161E.

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

CHARACTERISTIC	LIMITS			UNITS
	Min.	Typ.	Max.	
Supply Voltage Operating Range, V^+	4.5	5	5.5	V
Supply Current, I^+ (all inputs high)	-	3.5	8	mA
Output Current Low ($V_O = 2\text{ V}$)	18	25	32	mA
Output Current High ($V_O = 5.5\text{ V}$)	-	-	250	μA
Input Voltage High (logic "1" level)	2	-	-	V
Input Voltage Low (logic "0" level)	-	-	0.8	V
Input Current High (logic "1")	2 V	-30	-	μA
Input Current Low (logic "0")	0 V	-40	-	μA
Propagation Delay Time	t_{PHL}	-	2.6	μs
	t_{PLH}	-	1.4	

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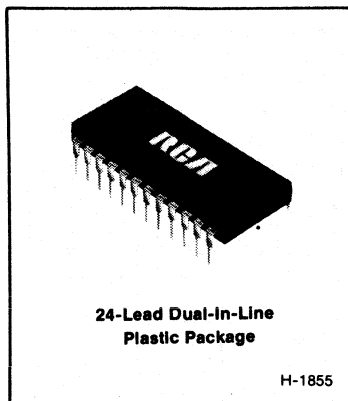
CA3161E



The photographs and dimensions represent a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

Dimensions and pad layout for the CA3161H.



2-Digit BCD-to-7-Segment Decoder/Driver

For Common-Anode LED Displays

Features

- Separate BCD inputs and segment outputs for each digit
- Input loading less than $15\ \mu\text{A}$
- I^2L logic with buffered inputs and outputs
- Internal input overrange protection circuit
- 5-V supply operation
- Internal biasing circuits
- Output drive capability of 25 mA per segment
- Open collector outputs drive indicators directly

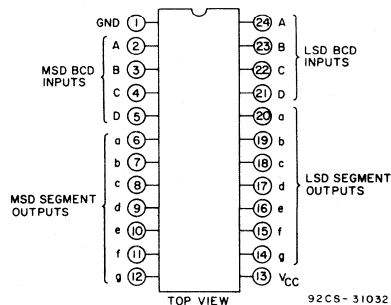
The RCA-CA3168E[•] is a monolithic integrated circuit intended for 2-digit display such as "numbers" for TV and "CB" channel selection, and other 0-99 numerical or counting for consumer or industrial indicator applications. It consists of two independent BCD-to-7-segment decoder/drivers. Two sets of BCD inputs are buffered with p-n-p differential amplifier stages internally referenced to 1.7 V. Each of the eight input terminals draws less than $15\ \mu\text{A}$ and is provided with an internal protection circuit.

Decoding is accomplished with I^2L ROM's. The fourteen output terminals are buffered with Darlington pairs driving common-emitter output transistors. Each output is capable of sinking 25 mA for an LED common-anode display device. The supply-voltage range (V_{CC}) is intended to be 4.5 V to 6 V. The output voltage (V_O) must not exceed 12 V, which provides for a wide range of common-anode voltage sources.

The CA3168E is supplied in the 24-lead dual-in-line plastic package.

[•]Formerly RCA Dev. Type No. TA10337

CA3168E TERMINAL ASSIGNMENT



MAXIMUM RATINGS, Absolute-Maximum Values:

SUPPLY-VOLTAGE, V_{CC}	6 V
INPUT-VOLTAGE (MIN./MAX.)	$-0.3/V_{CC}$ V
INPUT CURRENT (PROTECTION CIRCUIT)	± 10 mA
OUTPUT VOLTAGE, V_O	12 V
OUTPUT SEGMENT CURRENT, $I_{DISPLAY}$	25 mA
AMBIENT TEMPERATURE RANGE:	
Operating	0 to $+70^\circ\text{C}$
Storage	-55 to $+150^\circ\text{C}$
POWER DISSIPATION:	
Up to $+70^\circ\text{C}$	400 mW
Above $+70^\circ\text{C}$	derate linearly at 8.7 mW/ $^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10 seconds max.	$+265^\circ\text{C}$

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CA3168E

TYPICAL ELECTRICAL CHARACTERISTICS at $V_{CC} = 5\text{ V}$, $V_1 = \text{GND}$,

$V_{\text{DISP.}} = 12\text{ V}$, and $T_A = 25^\circ\text{C}$, See Fig. 2

Unless Otherwise Specified

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
Input Voltage High, V_{IH}		2.4	5	V_{CC}	V
Input Voltage Low, V_{IL}		0	—	0.6	V
Input Current High, I_{IH}	All BCD Inputs = 5 V	—	—	15	μA
Input Current Low, I_{IL}	All BCD inputs = 0 V	-10	—	—	μA
On-State Output Voltage, V_{OL}	$I_{O(\text{Sink})} = 25\text{ mA}$	—	—	1	V
Off-State Output Current, I_{OH}		—	5	50	μA
Power Supply Drain Current, I_{CC}	$V_{CC} = 6\text{ V}$	—	17	25	mA
Input Capacitance, C_i		—	5	—	pF

TRUTH TABLES

Most Significant Digit (MSD)

INPUTS	OUTPUTS	DISPLAY
D C B A	a b c d e f g	
0 0 0 0	0 0 0 0 0 0 1	0
0 0 0 1	1 0 0 1 1 1 1	1
0 0 1 0	0 0 1 0 0 1 0	2
0 0 1 1	0 0 0 0 1 1 0	3
0 1 0 0	1 0 0 1 1 0 0	4
0 1 0 1	0 1 0 0 1 0 0	5
0 1 1 0	0 1 0 0 0 0 0	6
0 1 1 1	0 0 0 1 1 1 1	7
1 0 0 0	0 0 0 0 0 0 0	8
1 0 0 1	0 0 0 0 1 0 0	9
1 0 1 0	0 1 1 0 0 0 1	C
1 0 1 1	0 0 0 1 0 0 0	A
1 1 0 0	0 0 1 1 0 0 0	P
1 1 0 1	0 1 1 0 0 0 0	E
1 1 1 0	1 1 1 1 1 1 0	—
1 1 1 1	1 1 1 1 1 1 1	BLANK

Least Significant Digit (LSD)

INPUTS	OUTPUTS	DISPLAY
D C B A	a b c d e f g	
0 0 0 0	0 0 0 0 0 0 1	0
0 0 0 1	1 0 0 1 1 1 1	1
0 0 1 0	0 0 1 0 0 1 0	2
0 0 1 1	0 0 0 0 1 1 0	3
0 1 0 0	1 0 0 1 1 0 0	4
0 1 0 1	0 1 0 0 1 0 0	5
0 1 1 0	0 1 0 0 0 0 0	6
0 1 1 1	0 0 0 1 1 1 1	7
1 0 0 0	0 0 0 0 0 0 0	8
1 0 0 1	0 0 0 0 1 0 0	9
1 0 1 0	1 0 0 1 0 0 0	H
1 0 1 1	1 0 0 0 0 1 1	J
1 1 0 0	1 1 1 0 0 0 1	L
1 1 0 1	0 1 1 1 0 0 0	F
1 1 1 0	1 1 1 1 1 1 0	—
1 1 1 1	1 1 1 1 1 1 1	BLANK

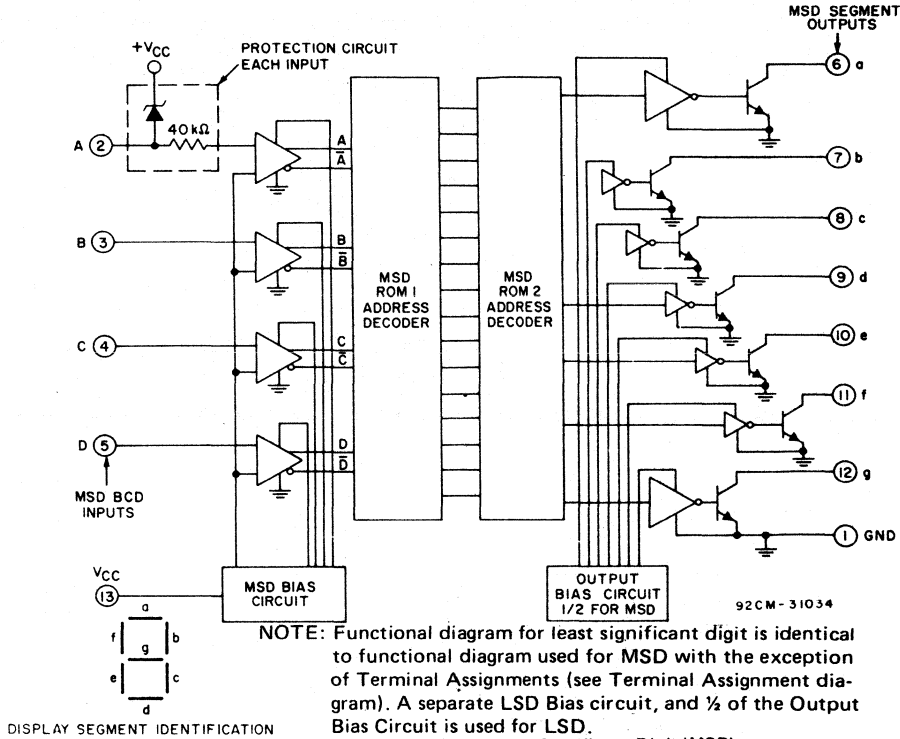


Fig. 1 - Functional diagram for Most Significant Digit (MSD).

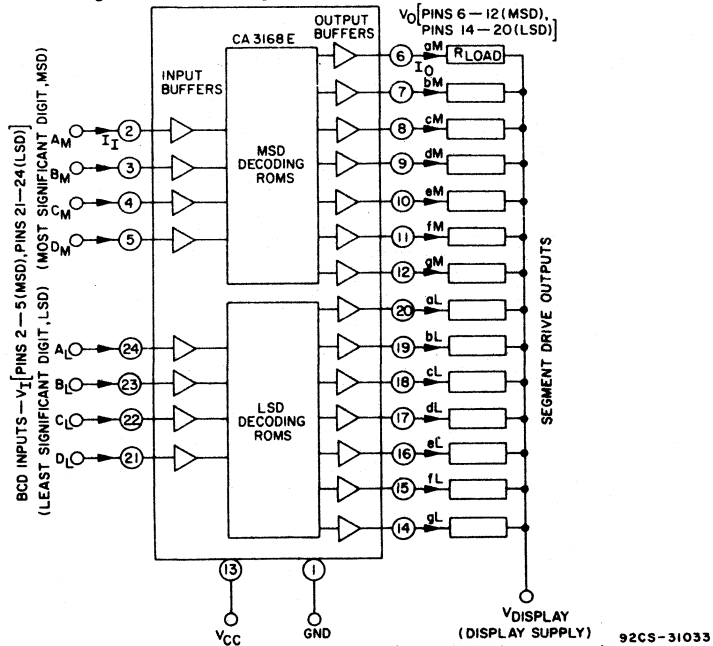


Fig. 2 - Test circuit.

Linear Integrated Circuits

CA3168E

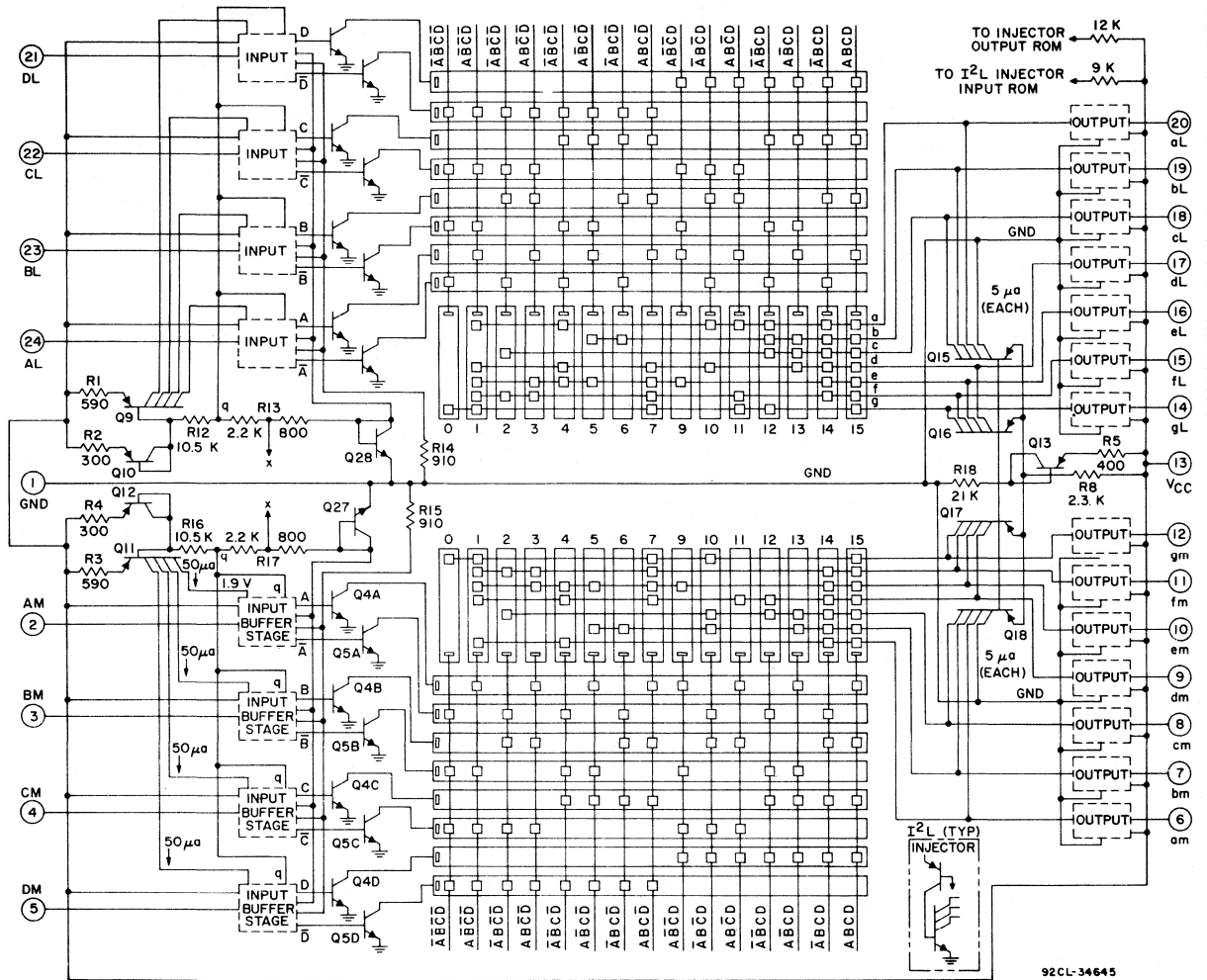


Fig. 3 - Schematic diagram of CA3168E.

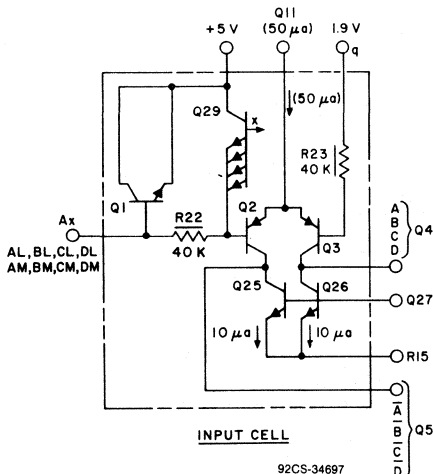


Fig. 4 - Schematic diagram of CA3168E input cell.

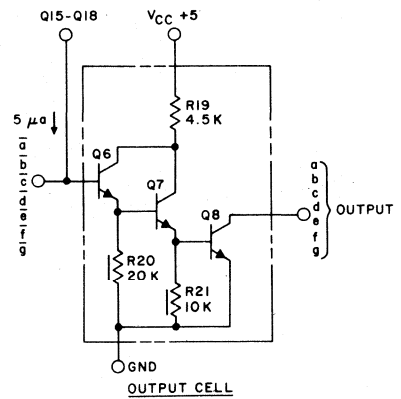
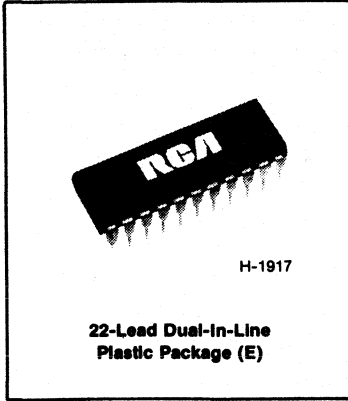


Fig. 5 - Schematic diagram of CA3168E output cell.

CA3207E, CA3208E

BiMOS Sequencer Driver and Segment Latch-Driver for Vacuum Fluorescent Displays



Features:

- Serial input, parallel output
- Total of 14 outputs
- CMOS and T²L compatible inputs
- Low-power CMOS Logic-Bipolar high-voltage output BiMOS process
- Use with vacuum fluorescent display
- Will operate in an output voltage range of 35 V to 55 V

Sequencer Driver (CA3207E)

- Sequentially turns on 1 of 14 characters (or 2 of 28 when used with 2 CA3208E's)
- Signal dimming through Gates 1 or 2

Latch Driver (CA3208E)

- Drives any combination of 14 outputs selected by DATA input
- Two or more devices may be interconnected by means of the CE and \overline{CE} inputs to drive more than 14 characters

The RCA-CA3207E and CA3208E*, sequence-driver and segment latch-driver, respectively, are used in combination to drive vacuum fluorescent display devices of up to 14 segments with up to 14 characters of display. The CA3207E selects the digit or character to be displayed in sequence and the CA3208E turns on the required number of segments of the character selected.

Each sequencer-driver will sequentially activate 14 characters. The sequencer-driver clock line may be used to drive the cross-coupled CE and \overline{CE} inputs of 2 segment-

latch drivers to provide for the display of up to 28 characters (see Fig. 12). The logic portion of both circuits use CMOS technology operating at 5 volts. The output drivers use bipolar technology and operate at supply voltages up to 55 volts. The CA3207E will source 40-mA per character and the CA3208E will source 7.5-mA per segment.

Both types are supplied in the 22-lead dual-in-line plastic package (E suffix), and they are also available in chip form (H suffix).

*Formerly Dev. Type No. TA10563 and TA10564, respectively.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE:

VCC, Pin 3 to GND, Pin 10.....	55 V
VDD, Pin 4 to GND, Pin 10.....	6 V

DEVICE DISSIPATION:

Up to T _A =+85°C.....	750 mW
Above T _A =+85°C.....	13 mW/°C

AMBIENT TEMPERATURE RANGE:

Operating.....	-40 to +85°C
Storage.....	-55 to +150°C

LEAD TEMPERATURE (DURING SOLDERING):

At distance 1/16 ± 1/32 in. (1.59 ± 0.79 mm) from case for 10 seconds max.	265°C
---	-------

Linear Integrated Circuits

CA3207E, CA3208E

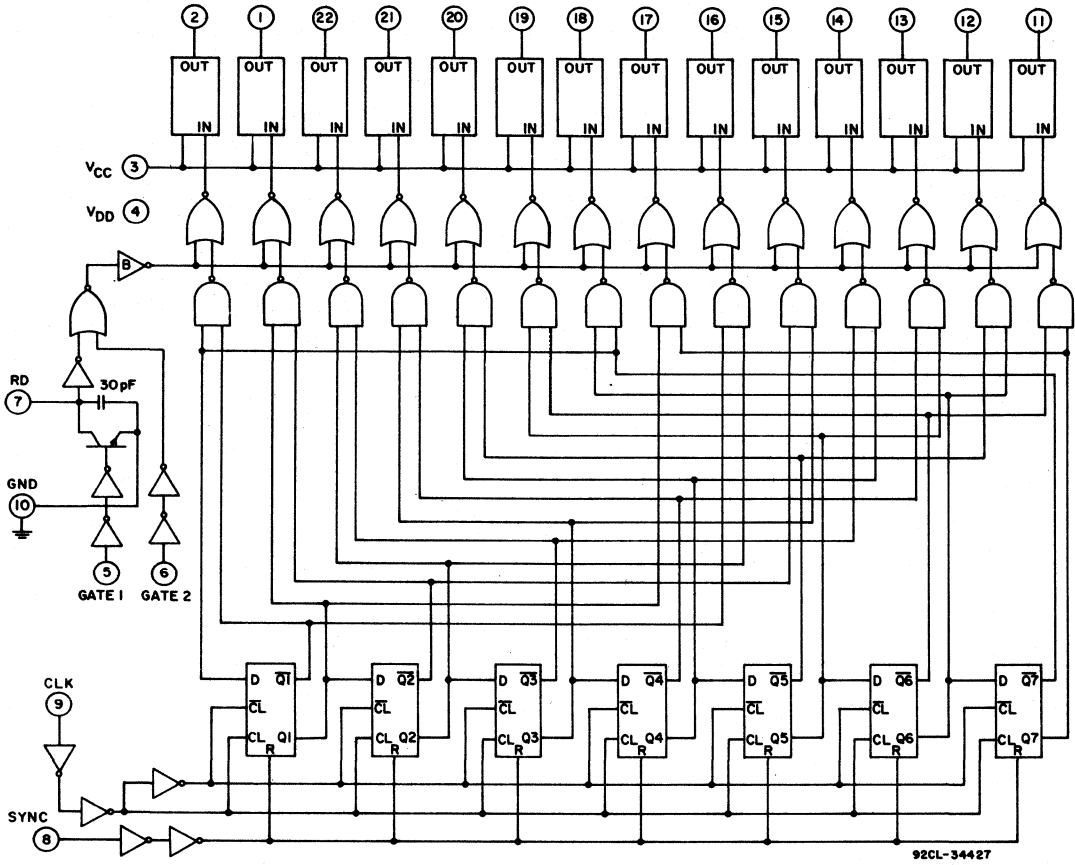
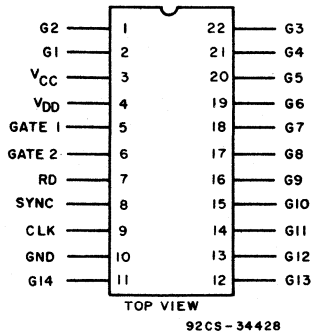


Fig. 1 - Sequencer-driver (CA3207E) logic diagram.



TERMINAL ASSIGNMENT CA3207E

CA3207E, CA3208E

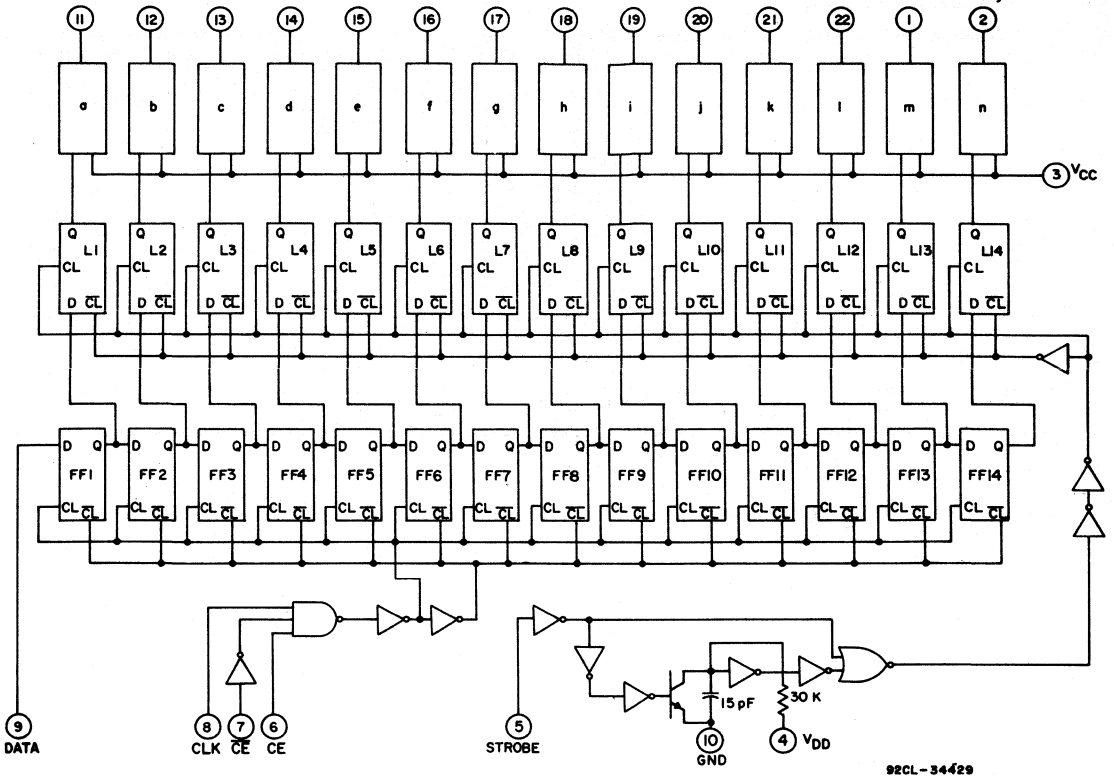
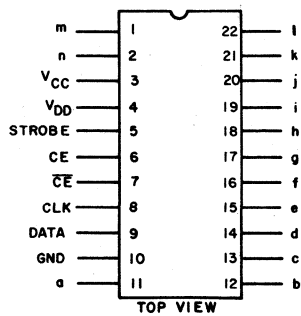


Fig. 2 - Segment-latch driver (CA3208E) logic diagram.



92CS-34430

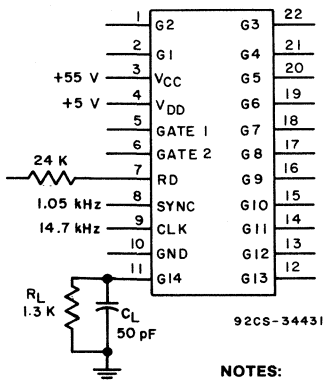
TERMINAL ASSIGNMENT
CA3208E

Linear Integrated Circuits

CA3207E, CA3208E

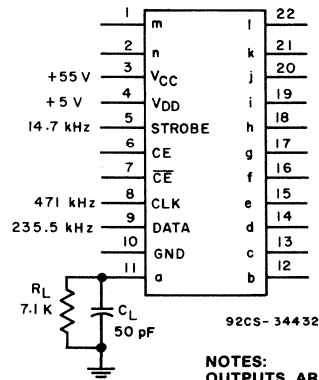
STATIC ELECTRICAL CHARACTERISTICS at $T_A=25^\circ\text{C}$,
 $V_{CC}=+55\text{ V}$, $V_{DD}=+5\text{ V}$, $C_L=50\text{ pF}$, See Fig. 3 and Fig. 4.

CHARACTERISTIC	TEST CONDITIONS	LIMITS				UNITS		
		CA3207E		CA3208E				
		Min.	Max.	Min.	Max.			
V_{CC} Supply Current	I_{CC}	No outputs "ON" Half outputs HIGH "ON"		—	10	—	—	mA
V_{DD} Supply Current	I_{DD}	All inputs HIGH		—	1	—	—	mA
		All inputs LOW		—	—	—	800	μA
		All inputs HIGH		—	—	—	1	
Input Current, Low-Level	I_{IL}	$V_{IN}=0\text{ V}$		—	1	—	1	μA
Input Current, High-Level	I_{IH}	$V_{IN}=5\text{ V}$		—	1	—	1	
Output Voltage, Low-Level	V_{OL}	$R_L=1.3\text{K}$		—	1	—	—	V
		$R_L=7.1\text{K}$		—	—	—	1	
Output Voltage, High-Level	V_{OH}	$I_{OH}=40\text{ mA}$		53	—	—	—	V
		$I_{OH}=7.5\text{ mA}$		—	—	53	—	
Input Low Voltage	V_{IL}			—	1.5	—	1.5	V
Input High Voltage	V_{IH}			3.5	—	3.5	—	



NOTES:
 OUTPUTS ARE PINS 1, 2 AND 11 THROUGH 22.
 OUTPUT LOADS ARE R_L (1.3 K) AND C_L (50 pF) WHICH RESULTS IN A 40-mA LOAD CURRENT.
 INPUT VOLTAGE LEVELS ARE 0 V AND 5 V.

Fig. 3 - Sequencer-driver (CA3207E) test circuit.



NOTES:
 OUTPUTS ARE PINS 1, 2 AND 11 THROUGH 22.
 OUTPUT LOADS ARE R_L (7.1 K) AND C_L (50 pF) WHICH RESULTS IN A 7.5-mA LOAD CURRENT.
 INPUT VOLTAGE LEVELS ARE 0 V AND 5 V.

Fig. 4 - Segment-latch driver (CA3208E) test circuit.

Data Conversion Circuits
CA3207E, CA3208E

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A=25^\circ\text{C}$, $V_{CC}=+55\text{ V}$, $V_{DD}=+5\text{ V}$, $C_L=50\text{ pF}$, $R_L=1.3\text{ K}$

CHARACTERISTIC	LIMITS		UNITS	
	CA3207E			
	Min.	Max.		
Sequencer-Driver, See Fig. 5				
Sync Pulse Width	t_{SW}	2	—	μs
Time Delay Gate 1:				
Input-to-Output Inhibit	t_{GI}	—	1.5	μs
Input-to-Output Enable	t_{GE}	—	2.3	μs
Lead Time Sync to Gate	t_{SG}	0.5	—	μs
Lead Time Clock to Gate	t_{CG}	0.5	—	
Clock Frequency	f_{CL}	—	14	kHz

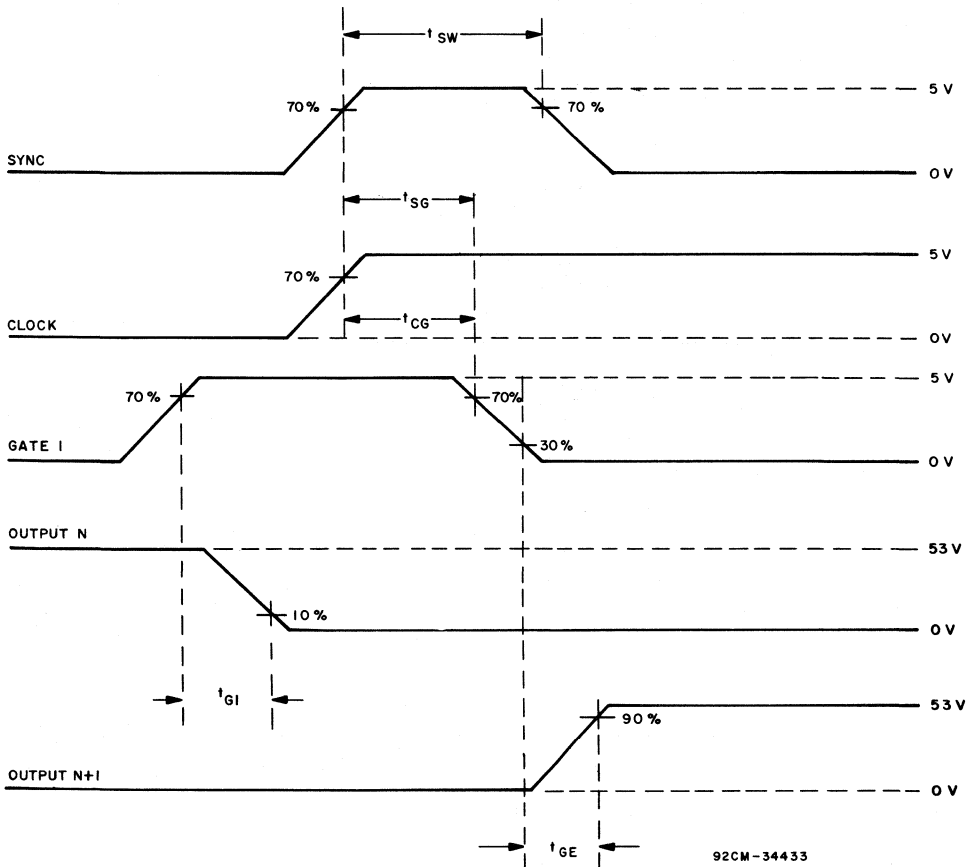


Fig. 5 - Sequencer-driver (CA3207E) timing waveforms.

Linear Integrated Circuits

CA3207E, CA3208E

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A=25^\circ\text{C}$, $V_{CC}=+5\text{ V}$, $V_{DD}=+5\text{ V}$, $C_L=50\text{ pF}$, $R_L=7.1\text{ K}$

CHARACTERISTIC	LIMITS		UNITS
	CA3208E		
	Min.	Max.	

Segment-Latch Driver, See Fig. 6

Time Delay:				
Strobe to Output	t_{PLH}	0.4	1.8	μs
Strobe to Output	t_{PHL}	—	2.6	
CE or $\overline{\text{CE}}$ to Clock	t_{CE}	0.8	—	
Input Data Set-Up Time	t_{SU}	0.5	—	μs
Input Data Hold Time	t_H	0.5	—	
Clock Frequency	f_{CL}	—	448	kHz
Data Frequency	f_D	—	224	

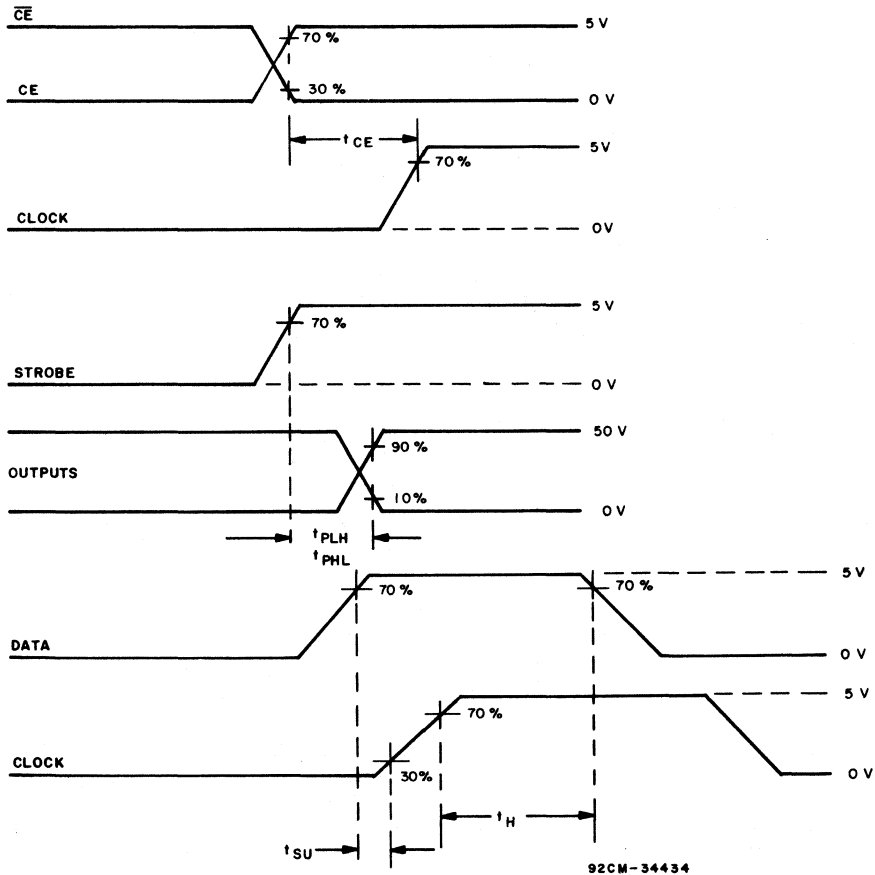


Fig. 6 - Segment-latch driver (CA3208E) timing waveforms.

Circuit Descriptions

Sequencer-Driver (CA3207E)

The CA3207E circuit consists of a 7-stage Johnson counter, which is reset by the positive transition of the sync pulse and which is clocked on the positive transitions of the clock pulse. The outputs of the counter are decoded to turn on one output driver at a time in sequence, for the period of one clock pulse (normally 70 μ s). The 14 output drivers are each capable of sourcing 40 mA of current and in a typical application will be connected to the grids of a vacuum fluorescent display, thereby performing a digit select function on a display of up to 14 characters. All outputs are set to zero by the application of a positive "1" level to either of the gate terminals, 5 and 6. The action of the 7-stage counter is unaffected by the presence of inhibit levels on the gate terminals. The gate terminals can be used for a controlled power down or for chopping where display dimmer is desired. The only difference between the two terminals is that gate 1, pin 5, has a delayed falling edge, which delays the release of the output drivers for a time determined by the value of the resistor connected between pin 7 and V_{DD} .

Segment-Latch Driver (CA3208E)

This circuit consists of a 14-bit shift register accepting serial data at pin 9 at a typical rate of 224 kHz and being clocked on the rising edge of the 448-kHz clock signal.

The leading edge of a 14-kHz strobe signal generates an internal strobe pulse through the one shot, which shifts the data, in parallel, from the shift register to the output latches, which in turn set the output drivers to the corresponding state. There are 14 output drivers, each capable of driving 7.5-mA at 55 volts, simultaneously. The drivers are normally connected to the anodes or segments of the vacuum fluorescent display. In a multi-character display, all corresponding segments in each character would be linked together. Activation of a particular character is made by the CA3207E Sequencer-Driver turning on the appropriate output and raising the grid of the display to a positive value.

Clock Enable (CE) and Clock Enable Not (\overline{CE}) pins are available for use in system applications. The first enables the chip with a logic level "1" and the second with a logic level "0".

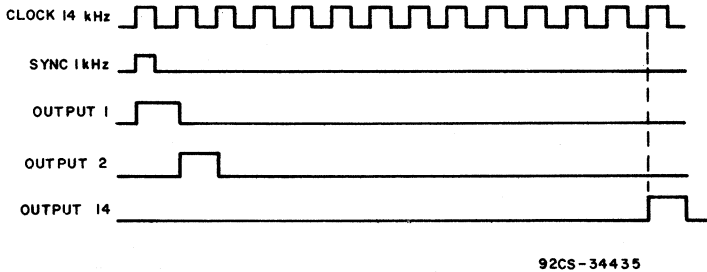


Fig. 7 - Sequencer driver (CA3207E) timing waveforms.

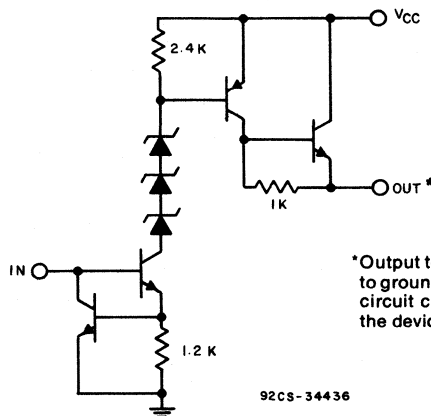
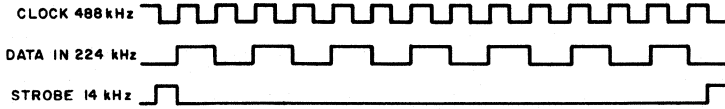


Fig. 8 - Sequencer driver (CA3207E) output circuit.

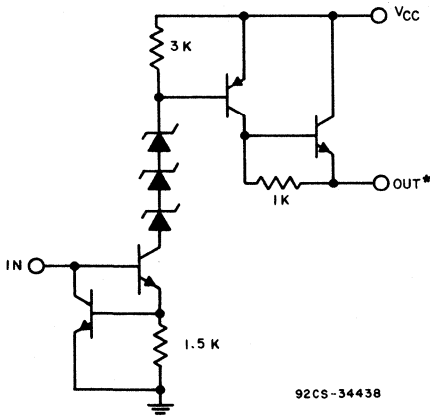
Linear Integrated Circuits

CA3207E, CA3208E



92CS-34437

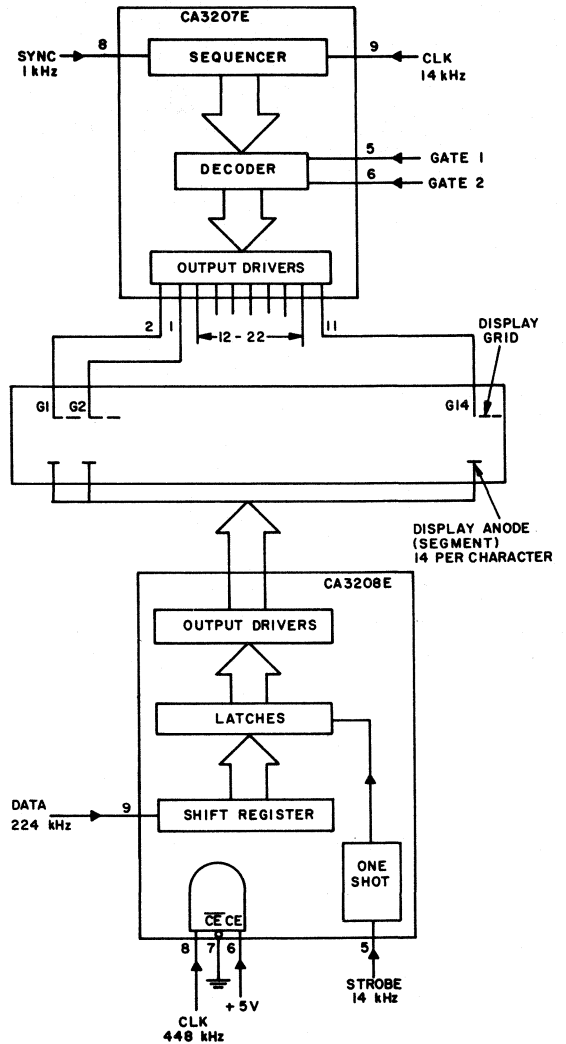
Fig. 9 - Segment-latch driver (CA3208E) timing waveforms.



92CS-34438

*Output terminals **must not** be shorted to ground because the resultant short-circuit current may cause damage to the device.

Fig. 10 - Segment latch-driver (CA3208E) output circuit.



NOTE: 2 DISPLAYS CAN BE OPERATED SIMULTANEOUSLY USING ONLY 1 SEQUENCER AND 2 SEGMENT-LATCH-DRIVERS
92CM-34439

Fig. 11 - Typical systems application of the CA3207E and CA3208E display circuits.

CA3207E, CA3208E

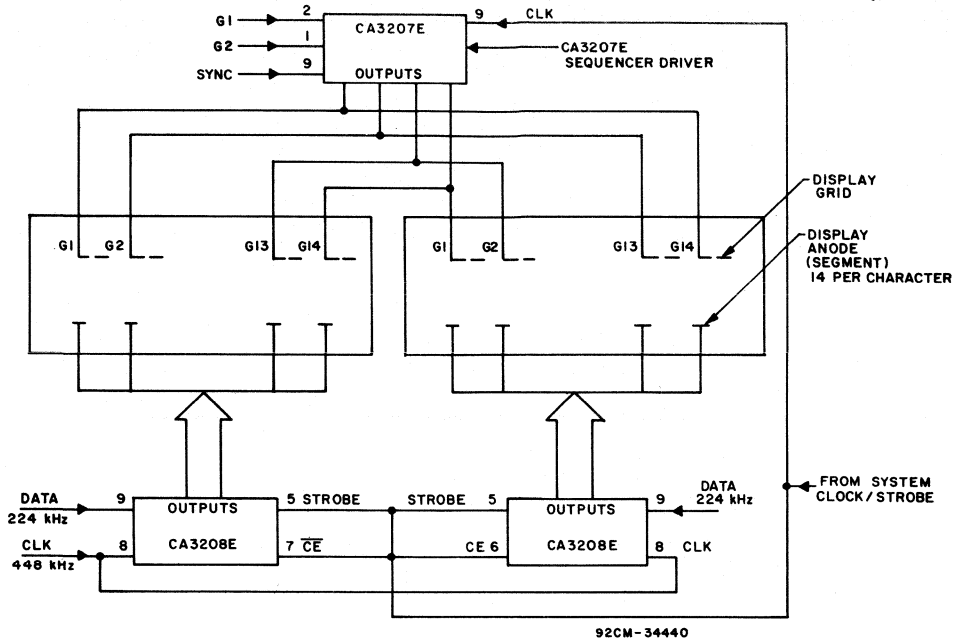
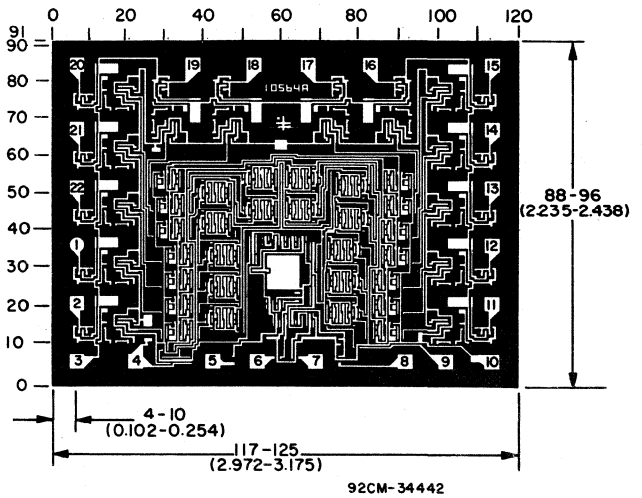
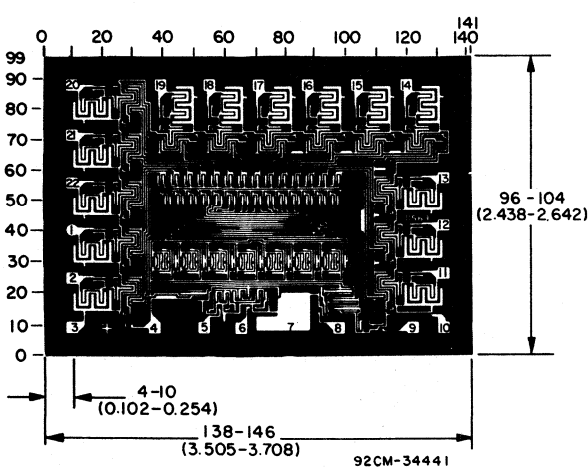


Fig. 12 - Typical systems application of the CA3207E and 2 CA3208E circuits for a total 28-character display.



Dimensions and pad layout for the CA3207H.

Dimensions and pad layout for the CA3208H.

The photographs and dimensions represent a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch).

Arrays

Technical Data

Amplifier/ Diode

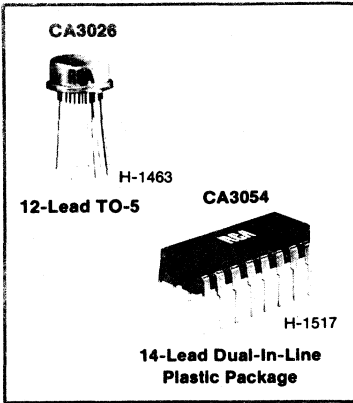
	Page
Amplifier	
CA3026.....	354
CA3035.....	362
CA3048.....	365
CA3049.....	372
CA3052.....	377
CA3054.....	354
CA3060.....	See Page 224
CA3102.....	372
Diode	
CA3019.....	384
CA3039.....	386
CA3141.....	390

Transistor

	Page
CA1724.....	393
CA1725.....	393
CA3018.....	396
CA3036.....	402
CA3045.....	404
CA3046.....	404
CA3050.....	410
CA3051.....	410
CA3081.....	332
CA3082.....	332
CA3083.....	418
CA3084.....	422
CA3086.....	427
CA3093.....	432
CA3096.....	438
CA3097.....	448
CA3118.....	459
CA3127.....	466
CA3128.....	471
CA3138.....	473
CA3146.....	459
CA3183.....	459
CA3227.....	476
CA3246.....	476
CA3600 Δ	479

Δ CMOS types

CA3026, CA3054



Transistor Array - Dual Independent Differential Amplifiers

For Low Power Applications
at Frequencies from DC to 120 MHz

Features

- Two differential amplifiers on a common substrate
- Independently accessible inputs and outputs
- Maximum input offset voltage - ± 5 mV
- Full military temperature-range capability - -55°C to $+125^{\circ}\text{C}$
- Limited temperature range - 0°C to 85°C for CA3054

The CA3026 and CA3054 each consists of two independent differential amplifiers with associated constant-current transistors on a common monolithic substrate. The six n-p-n transistors which comprise the amplifiers are general-purpose devices which exhibit low 1/f noise and a value of f_T in excess of 300 MHz. These features make the CA3026 and CA3054 useful from dc to 120 MHz. Bias and load resistors have been omitted to provide maximum application flexibility.

The monolithic construction of the CA3026 and CA3054 provides close electrical and thermal matching of the amplifiers. This feature makes these devices particularly useful in dual-channel applications where matched performance of the two channels is required.

The CA3026 is supplied in a hermetic 12-lead TO-5-style package and is rated for full military operating-temperature range of -55°C to $+125^{\circ}\text{C}$.

The CA3054 is supplied in a 14-lead plastic dual-in-line package with a limited temperature range. The availability of extra terminals allows the introduction of an independent substrate connection for maximum flexibility.

Applications

- Dual sense amplifiers
- Dual Schmitt triggers
- Multifunction combinations - RF/Mixer/Oscillator; Converter/IF
- IF amplifiers (differential and/or cascode)
- Product detectors
- Doubly balanced modulators and demodulators
- Balanced quadrature detectors
- Cascade limiters
- Synchronous detectors
- Pairs of balanced mixers
- Synthesizer mixers
- Balanced (push-pull) cascode amplifiers

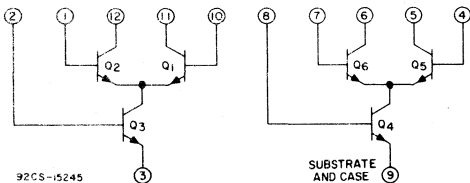


Fig. 1a - Schematic Diagram for CA3026.

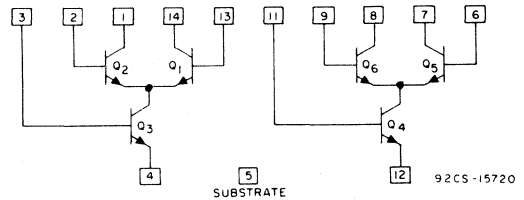


Fig. 1b - Schematic Diagram for CA3054.

CAUTION: Substrate **MUST** be maintained negative with respect to all collector terminals of this device. See Maximum Voltage Ratings chart.

CA3026, CA3054

MAXIMUM RATINGS, ABSOLUTE-MAXIMUM VALUES, AT $T_A = 25^\circ\text{C}$

Power Dissipation, P:	CA3026	CA3054	
Any one transistor	300	300	mW
Total package	600	750	mW
For $T_A > 55^\circ\text{C}$	Derate at 5	6.67	mW/ $^\circ\text{C}$
Temperature Range:			
Operating	-55 to +125	-40 to +85	$^\circ\text{C}$
Storage	-65 to +150	-65 to +150	$^\circ\text{C}$

The following ratings apply for each transistor in the device:

Collector-to-Emitter Voltage, V_{CE0}	15	V
Collector-to-Base Voltage, V_{CBO}	20	V
Collector-to-Substrate Voltage, V_{CISO}^*	20	V
Emitter-to-Base Voltage, V_{EBO}	5	V
Collector Current, I_C	50	mA

LEAD TEMPERATURE (During Soldering)

At distance $1/16 \pm 1/32$ inch ($1.59 \pm 0.79\text{mm}$)
 from case for 10 seconds max. $+265^\circ\text{C}$

* The collector of each transistor of the CA3026 and CA3054 is isolated from the substrate by an integral diode. The substrate must be connected to a voltage which is more negative than any collector voltage in order to maintain isolation between transistors and provide

for normal transistor action. The substrate should be maintained at signal (AC) ground by means of a suitable grounding capacitor, to avoid undesired coupling between transistors.

Maximum Voltage Ratings

The following chart gives the range of voltages which can be applied to the terminals listed vertically with respect to the terminals listed horizontally. For example, the voltage range between vertical terminal 1[†] and horizontal terminal 3[†] is +15 to -5 volts.

† For CA3026; corresponding terminals for CA3054 are vertical terminal 2 and horizontal terminal 4.

CA3054 TERMINAL No.	CA3026 TERMINAL No.	13	14	1	2	3	4	6	7	8	9	11	12	5
13	10	0 -20	*	+5 -5	*	+15 -5	*	*	*	*	*	*	*	*
14	11		*	*	*	+20 0	*	*	*	*	*	*	*	+20 0
1	12				+20 0	+20 0	*	*	*	*	*	*	*	+20 0
2	1					+15 -5	*	*	*	*	*	*	*	*
3	2						+1 -5	*	*	*	*	*	*	*
4	3							*	*	*	*	*	*	*
6	4								0 -20	+5 -5	*	+15 -5	*	*
7	5									*	*	*	*	+20 0
8	6										+20 0	*	*	+20 0
9	7											*	+15 -5	*
11	8												+1 -5	*
12	9													*
5	9													Ref Sub- strate

* Voltages are not normally applied between these terminals. Voltages appearing between these terminals will be safe if the specified limits between all other terminals are not exceeded.

Note 1: In the CA3026 terminal No.9 is connected to the emitter of Q_4 , the reference substrate, and the case; therefore, the case should not be grounded. Two terminal 9 columns (CA3026) appear in the voltage rating chart because it is a composite chart for both the CA3026 and the CA3054. Whenever an asterisk is shown in one column 9 and a rating is shown in the other column 9, the asterisk should be ignored.

Maximum Current Ratings

CA3054 TERMINAL No.●	CA3026 TERMINAL No.	I_{IN} mA	I_{OUT} mA
13	10	5	0.1
14	11	50	0.1
1	12	50	0.1
2	1	5	0.1
3	2	5	0.1
4	3	0.1	-50
6	4	5	0.1
7	5	50	0.1
8	6	50	0.1
9	7	5	0.1
11	8	5	0.1
12	9	0.1	50

● Terminal No.10 of CA3054 is not used

Linear Integrated Circuits

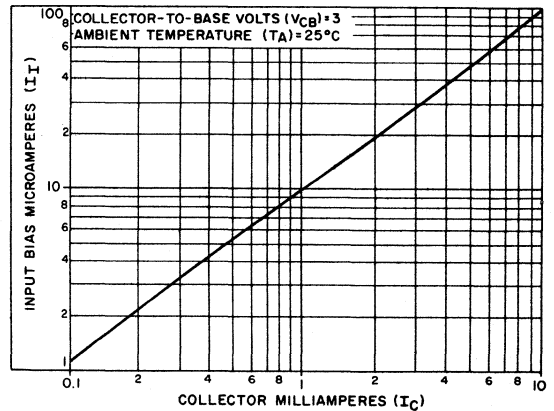
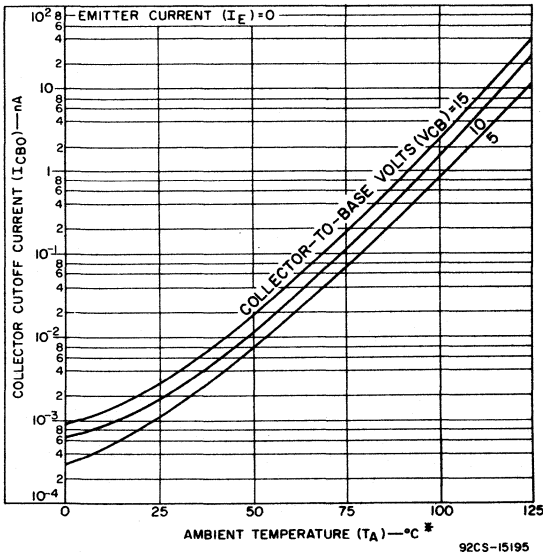
CA3026, CA3054

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

CHARACTERISTICS	SYMBOLS	TEST CONDITIONS	TEST CIRCUIT	CA3026 CA3054 LIMITS			UNITS	TYPICAL CHARACTERISTICS CURVES	
			FIG.	MIN.	TYP.	MAX.		FIG.	
STATIC CHARACTERISTICS									
For Each Differential Amplifier									
Input Offset Voltage	V_{IO}	$V_{CB} = 3\text{ V}$ $I_{E(Q3)} = I_{E(Q4)} = 2\text{ mA}$	-	-	0.45	5	mV	6	
Input Offset Current	I_{IO}		-	-	0.3	2	μA	7	
Input Bias Current	I_I		-	-	10	24	μA	3	
Quiescent Operating Current Ratio	$\frac{I_{C(Q1)} \text{ or } I_{C(Q5)}}{I_{C(Q2)} \text{ or } I_{C(Q6)}}$		-	-	0.98 to 1.02	-	-	3	
Temperature Coefficient Magnitude of Input-Offset Voltage	$\frac{ \Delta V_{IO} }{\Delta T}$		-	-	1.1	-	$\mu\text{V}/^\circ\text{C}$	5	
For Each Transistor									
DC Forward Base-to-Emitter Voltage	V_{BE}	$V_{CB} = 3\text{ V}$	$I_C = 50\ \mu\text{A}$	-	-	0.630	0.700	V	6
			1 mA	-	-	0.715	0.800		
			3 mA	-	-	0.750	0.850		
			10 mA	-	-	0.800	0.900		
Temperature Coefficient of Base-to-Emitter Voltage	$\frac{\Delta V_{BE}}{\Delta T}$	$V_{CB} = 3\text{ V}, I_C = 1\text{ mA}$	-	-	-1.9	-	$\mu\text{V}/^\circ\text{C}$	4	
Collector-Cutoff Current	I_{CBO}	$V_{CB} = 10\text{ V}, I_E = 0$	-	-	0.002	100	nA	2	
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 1\text{ mA}, I_B = 0$	-	15	24	-	V	-	
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 10\ \mu\text{A}, I_E = 0$	-	20	60	-	V	-	
Collector-to-Substrate Breakdown Voltage	$V_{(BR)CIO}$	$I_C = 10\ \mu\text{A}, I_{CI} = 0$	-	20	60	-	V	-	
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 10\ \mu\text{A}, I_C = 0$	-	5	7	-	V	-	
DYNAMIC CHARACTERISTICS									
Common-Mode Rejection Ratio For Each Amplifier	CMR	$V_{CC} = 12\text{ V}$ $V_{EE} = -6\text{ V}$ $V_X = -3.3\text{ V}$ $f = 1\text{ kHz}$	8a	-	100	-	dB	8b	
AGC Range, One Stage	AGC		9a	-	75	-	dB	9b	
Voltage Gain, Single Stage Double-Ended Output	A		9a	-	32	-	dB	9b	
AGC Range, Two Stage	AGC		10a	-	105	-	dB	10b	
Voltage Gain, Two Stage Double-Ended Output	A		10a	-	60	-	dB	10b	
Low-Frequency, Small-Signal Equivalent-Circuit Characteristics: (For Single Transistor)									
Forward Current-Transfer Ratio	h_{fe}	$f = 1\text{ kHz}, V_{CE} = 3\text{ V}, I_C = 1\text{ mA}$	-	-	110	-	-	11	
Short-Circuit Input Impedance	h_{ie}		-	-	3.5	-	$\text{k}\Omega$	11	
Open-Circuit Output Impedance	h_{oe}		-	-	15.6	-	μmho	11	
Open-Circuit Reverse Voltage-Transfer Ratio	h_{re}		-	-	1.8×10^{-4}	-	-	11	

DYNAMIC CHARACTERISTICS CONT'D.								
1/f Noise Figure (For Single Transistor)	NF	$f = 1 \text{ kHz}, V_{CE} = 3 \text{ V}$	-	-	3.25	-	dB	-
Gain-Bandwidth Product (For Single Transistor)	f_T	$V_{CE} = 3 \text{ V}, I_C = 3 \text{ mA}$	-	-	550	-	MHz	12
Admittance Characteristics; Differential Circuit Configuration: (For Each Amplifier)								
Forward Transfer Admittance	y_{21}	$V_{CB} = 3 \text{ V}$ Each Collector $I_C \approx 1.25 \text{ mA}$ $f = 1 \text{ MHz}$	-	-	$-20 + j0$	-	mmho	13a
Input Admittance	y_{11}		-	-	$0.22 + j0.1$	-	mmho	13b
Output Admittance	y_{22}		-	-	$0.01 + j0$	-	mmho	13c
Reverse Transfer Admittance	y_{12}		-	-	$-0.003 + j0$	-	mmho	13d
Admittance Characteristics; Cascode Circuit Configuration: (For Each Amplifier)								
Forward Transfer Admittance	y_{21}	$V_{CB} = 3 \text{ V}$ Total Stage $I_C \approx 2.5 \text{ mA}$ $f = 1 \text{ MHz}$	-	-	$68 - j0$	-	mmho	14a
Input Admittance	y_{11}		-	-	$0.55 + j0$	-	mmho	14b
Output Admittance	y_{22}		-	-	$0 + j0.02$	-	mmho	14c
Reverse Transfer Admittance	y_{12}		-	-	$0.004 - j0.005$	-	μmho	14d
Noise Figure	NF	$f = 100 \text{ MHz}$	-	-	8	-	dB	-

TYPICAL STATIC CHARACTERISTICS



* For CA3054: use data from 0°C to 85°C only

Fig. 2 - Collector-to-base cutoff current vs ambient temperature for each transistor.

Fig. 3 - Input bias current characteristic vs collector current for each transistor.

TYPICAL STATIC CHARACTERISTICS

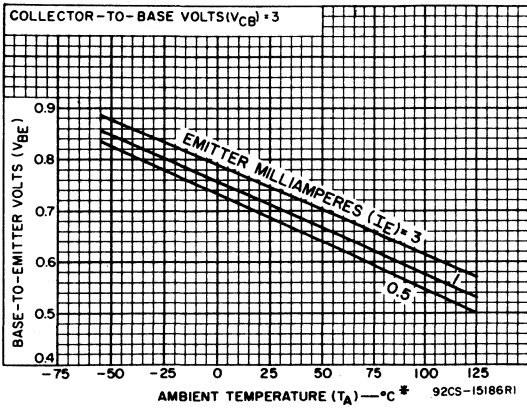


Fig. 4 - Base-to-emitter voltage characteristic for each transistor vs ambient temperature.

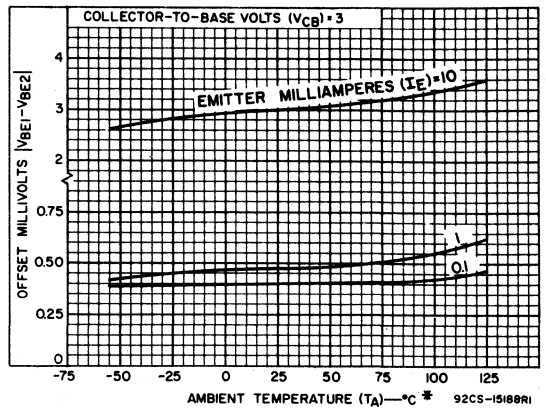


Fig. 5 - Offset voltage characteristic vs ambient temperature for differential pairs.

* For CA3054: use data from 0°C to 85°C only

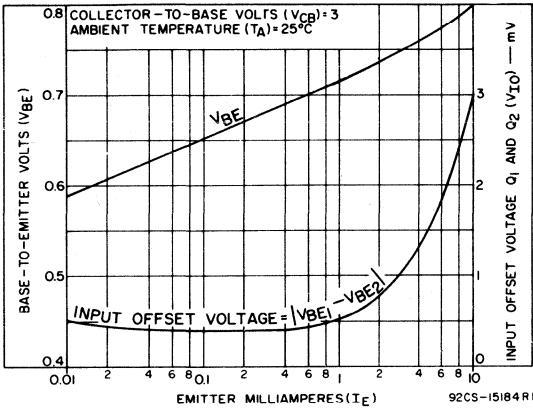


Fig. 6 - Static base-to-emitter voltage characteristic and input offset voltage for differential pairs vs emitter current.

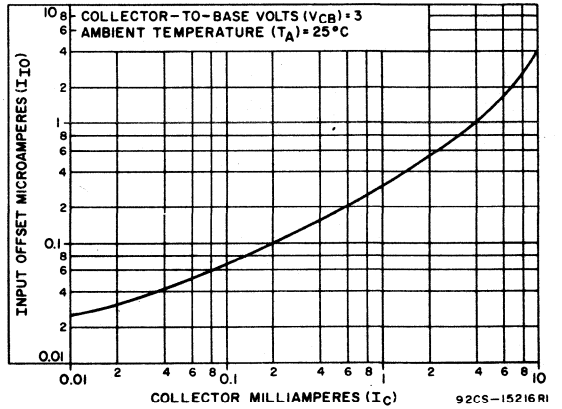


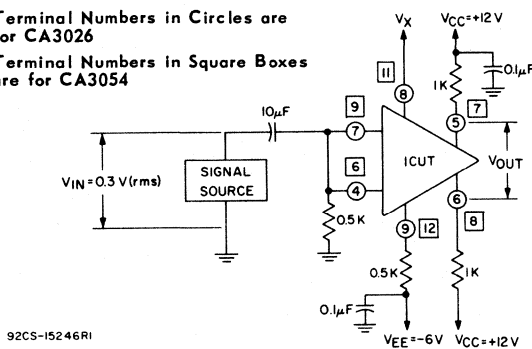
Fig. 7 - Input offset current for matched differential pairs vs collector current.

TYPICAL DYNAMIC CHARACTERISTICS

COMMON MODE REJECTION RATIO

Terminal Numbers in Circles are for CA3026

Terminal Numbers in Square Boxes are for CA3054



(a) Test setup

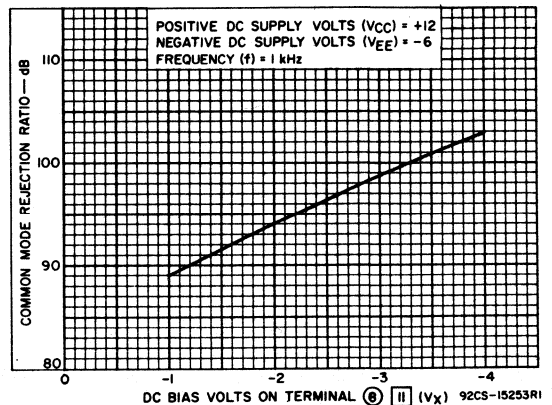


Fig. 8

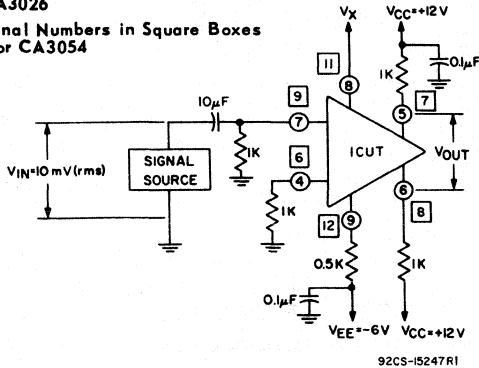
(b) Characteristic

TYPICAL DYNAMIC CHARACTERISTICS (cont'd)

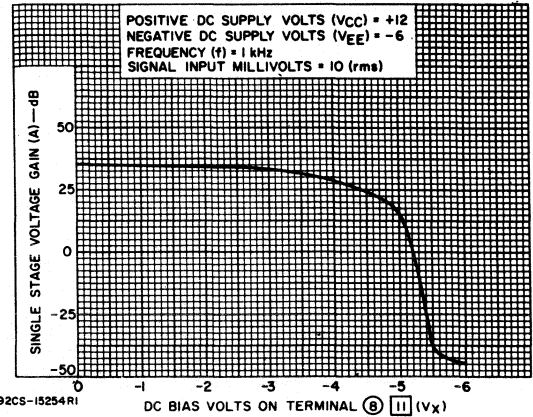
SINGLE-STAGE VOLTAGE GAIN

Terminal Numbers in Circles are for CA3026

Terminal Numbers in Square Boxes are for CA3054



(a) Test setup



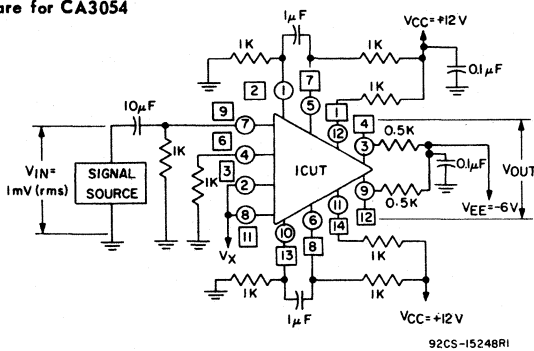
(b) Characteristic

Fig.9

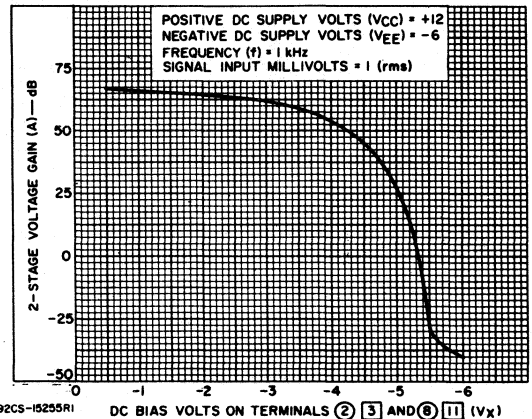
TWO-STAGE VOLTAGE GAIN

Terminal Numbers in Circles are for CA3026

Terminal Numbers in Square Boxes are for CA3054



(a) Test setup



(b) Characteristic

Fig.10

TYPICAL DYNAMIC CHARACTERISTICS FOR EACH TRANSISTOR

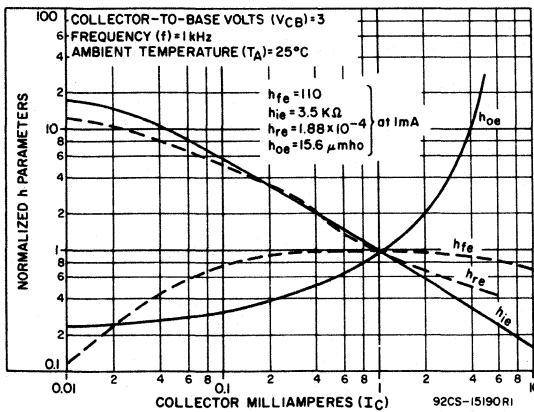


Fig.11 - Forward current-transfer ratio (h_{fe}), short-circuit input impedance (h_{ie}), open-circuit output impedance (h_{oe}), and open-circuit reverse voltage-transfer ratio (h_{re}) vs collector current for each transistor.

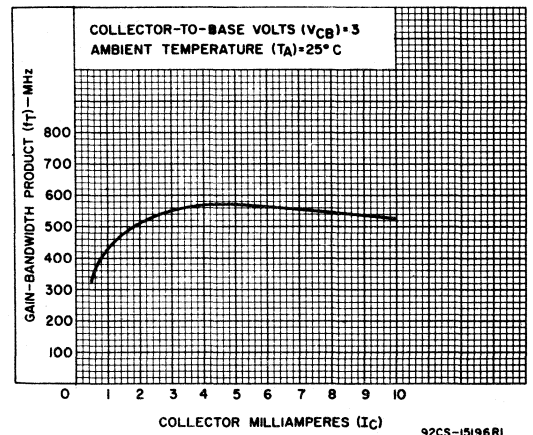


Fig.12 - Gain-bandwidth product (f_T) vs collector current.

Linear Integrated Circuits

CA3026, CA3054

TYPICAL DYNAMIC CHARACTERISTICS FOR EACH DIFFERENTIAL AMPLIFIER

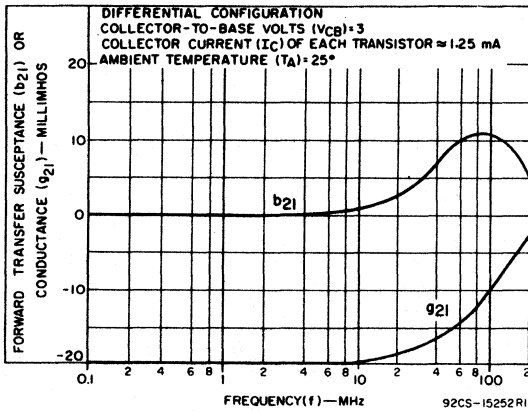


Fig. 13(a) - Forward transfer admittance (Y_{21}) vs frequency.

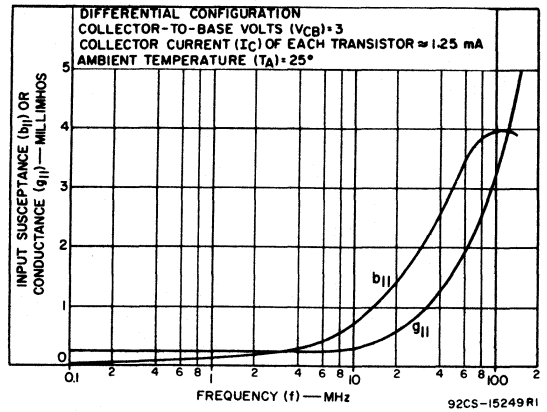


Fig. 13(b) - Input admittance (Y_{11}).

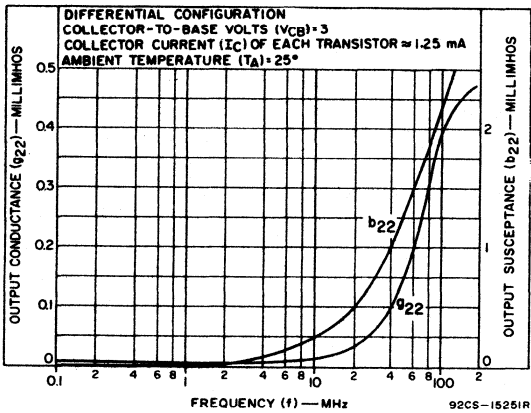


Fig. 13(c) - Output admittance (Y_{22}) vs frequency.

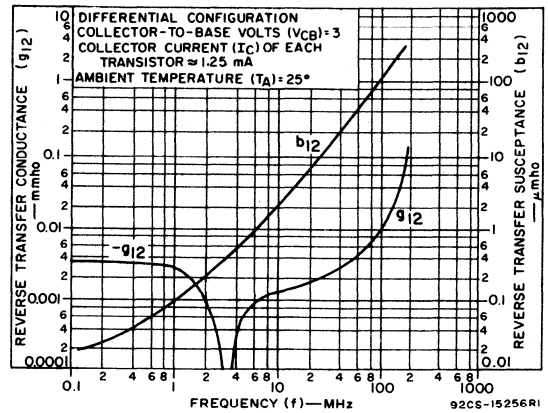


Fig. 13(d) - Reverse transfer admittance (Y_{12}) vs frequency.

TYPICAL DYNAMIC CHARACTERISTICS FOR EACH CASCODE AMPLIFIER

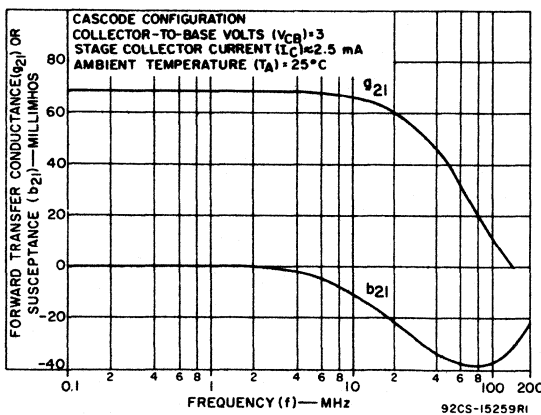


Fig. 14(a) - Forward transfer admittance (Y_{21}) vs frequency.

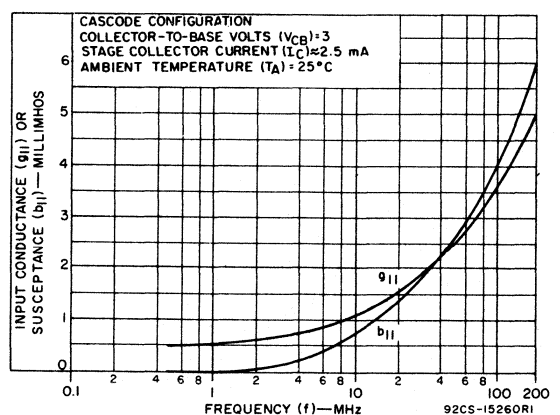


Fig. 14(b) - Input admittance (Y_{11}) vs frequency.

TYPICAL CHARACTERISTICS FOR EACH CASCODE AMPLIFIER (cont'd)

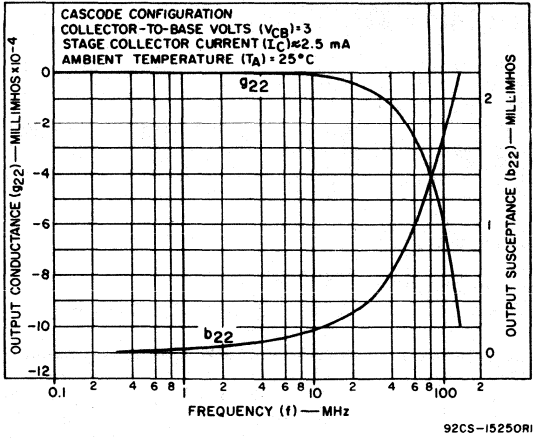


Fig.14(c) - Output admittance (Y_{22}) vs frequency.

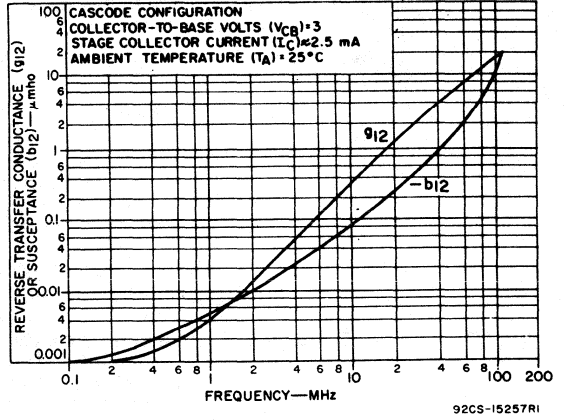
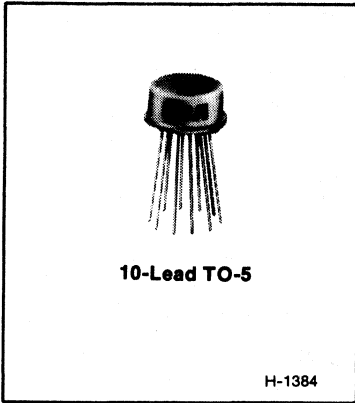


Fig.14(d) - Reverse transfer admittance (Y_{12}) vs frequency.

CA3035, CA3035V1



Ultra-High-Gain Wide-Band Amplifier Array

Features:

- Three separate amplifiers – gain and bandwidth for each amplifier can be adjusted with suitable external circuitry
- Amplifiers operable independently or in cascade
- Exceptionally high cascade voltage gain – 129 dB typ. at 40 kHz
- Low noise performance
- Wide-band response
- All amplifiers single-ended – only one power supply required
- Wide operating temperature range – -55°C to $+125^{\circ}\text{C}$

- Built-in temperature compensation
- Hermetically sealed, all-welded 10-lead TO-5 style metal package with straight or formed leads

Applications:

- Three individual general-purpose amplifiers
- Ideal for service in remote-control amplifiers – e.g., TV receivers
- Available in two electrically identical versions: CA3035 with straight leads; CA3035V1 with formed leads

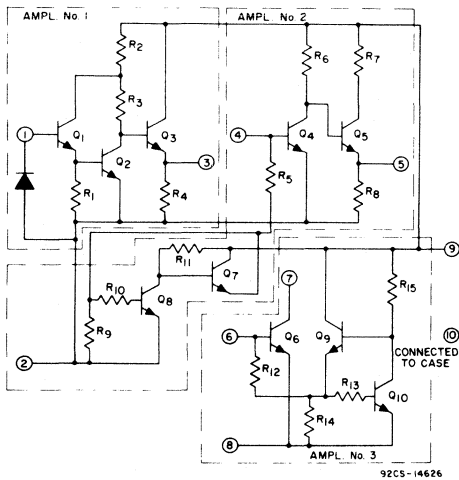


Fig. 1 — Schematic Diagram for CA3035 and CA3035V1

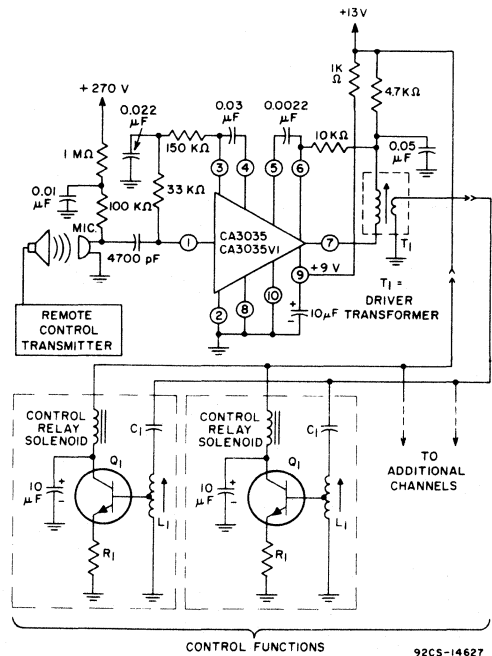


Fig. 2 — Typical Remote Control System

CA3035, CA3035V1

ABSOLUTE-MAXIMUM RATINGS:

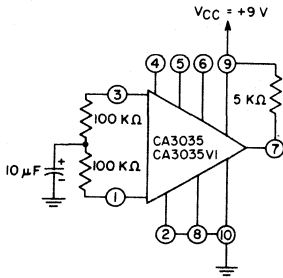
Operating Temperature Range -55°C to +125°C
 Storage Temperature Range -65°C to +200°C
 Device Dissipation 300 mW
 Input Voltage 1 V p-p
 Supply Voltage +15V

ELECTRICAL CHARACTERISTICS AT T_A = 25°C

CHARACTERISTICS	SYMBOLS	SPECIAL TEST CONDITIONS	TEST CIRCUITS AND CHARACTERISTICS CURVES	LIMITS			UNITS
				CA3035, CA3035V1			
				Min.	Typ.	Max.	
STATIC CHARACTERISTICS							
Quiescent Operating Voltage	V3	V _{CC} = +9V	Fig.3	-	2	-	V
	V5			-	1.9	-	V
	V7			-	4.9	-	V
Total Current Drain	I _d	V _{CC} = +9V, R _{L3} = 5KΩ	Fig.3	3.5	5	7.5	mA
DYNAMIC CHARACTERISTICS							
Voltage Gain: Amplifier No.1 Amplifier No.2 Amplifier No.3	A ₁	f = 40 kHz, V _{CC} = +9V		40	44	-	dB
	A ₂			40	46	-	dB
	A ₃			38	42	-	dB
Output Voltage Swing	V _{out}	R _{L1} = 10KΩ R _{L2} = 10KΩ R _{L3} = 5KΩ Sinusoidal Output, V _{CC} = +9V		-	2	-	V _{p-p}
	V _{1out}			-	2.6	-	V _{p-p}
	V _{2out} V _{3out}			-	8	-	V _{p-p}
Input Resistance: Amplifier No.1 Amplifier No.2 Amplifier No.3	R _{1in}	f = 40 kHz		-	50K	-	Ω
	R _{2in}			-	2K	-	Ω
	R _{3in}			-	670	-	Ω
Output Resistance	R _{1out}	f = 40 kHz		-	270	-	Ω
	R _{2out}			-	170	-	Ω
	R _{3out}			-	100K	-	Ω
Bandwidth at -3dB point: Amplifier No.1 Amplifier No.2 Amplifier No.3	BW ₁	V _{CC} = +9V	Fig.5	-	500	-	kHz
	BW ₂		Fig.6	-	2.5	-	MHz
	BW ₃		Fig.7	-	2.5	-	MHz
Noise Figure Amplifier No.1	NF ₁	f = 1 kHz, R _S = 1KΩ	Fig.4	-	6	7	dB
Sensitivity		V _{CC} = +13 V Relay (K ₁) Current = 7.5 mA	Fig.2	-	100	150	μV

CA3035, CA3035V1

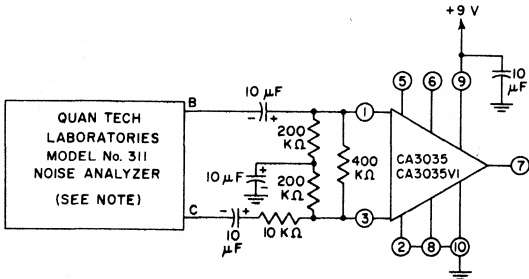
STATIC CHARACTERISTICS TEST CIRCUIT



92CS-14625

Fig. 3

NOISE FIGURE TEST CIRCUIT

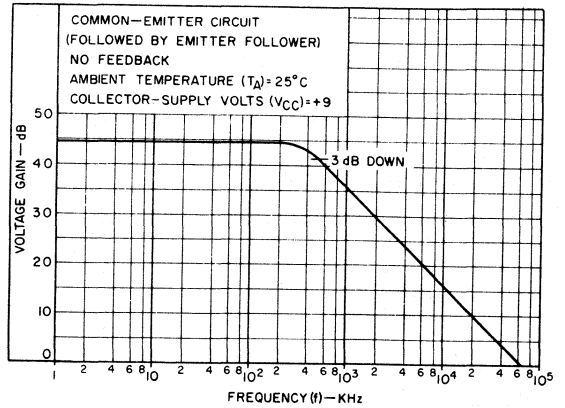


92CS-14631

NOTE: SET ALL INTERNAL POWER SUPPLIES ON QUAN TECH NOISE ANALYZER TO ZERO VOLTS.

Fig. 4

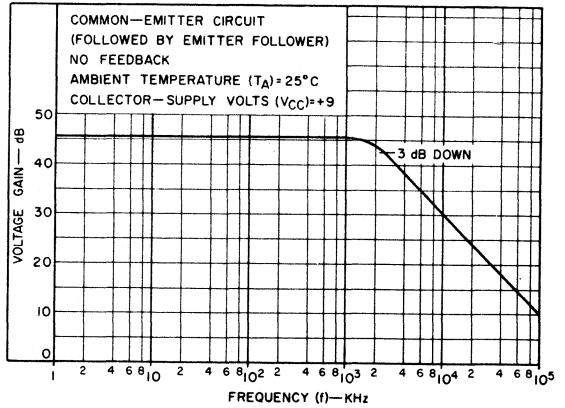
TYPICAL 1st-AMPLIFIER RESPONSE



92CS-14635

Fig. 5

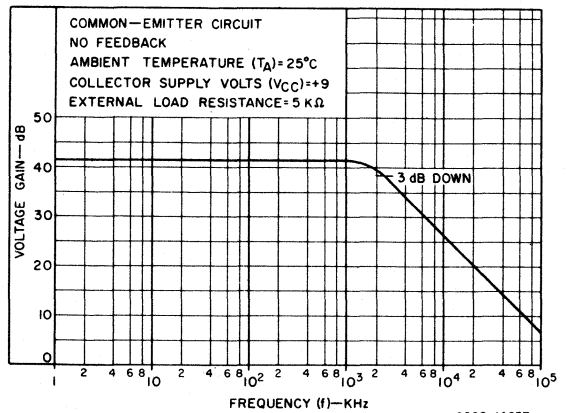
TYPICAL 2nd-AMPLIFIER RESPONSE



92CS-14636

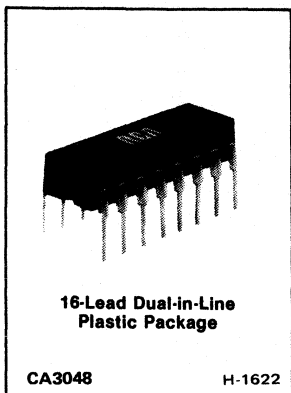
Fig. 6

TYPICAL 3rd-AMPLIFIER RESPONSE



92CS-14637

Fig. 7



Four Independent AC Amplifiers

For Low-Noise and General AC Applications
In Industrial Service

FEATURES

- Four AC amplifiers on a common substrate
 - Independently accessible inputs and outputs
 - Operates from single-ended supply
- EACH AMPLIFIER
- Noise figure at 1kHz..... 2 dB typ.
 - High voltage gain..... 53 dB min.

The RCA CA3048 is a silicon monolithic integrated circuit consisting of four independent identical AC amplifiers which can operate from a single-ended power supply.

The amplifiers include internal DC bias and feedback to provide temperature-stabilized operation. They may be used in a wide variety of AC applications in which operational amplifiers have previously been used.

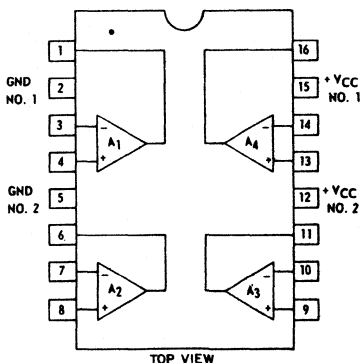
Each high gain amplifier has a high impedance non-inverting input, and a lower impedance inverting input for the application of feedback. Two power-supply terminals and two ground terminals are provided to reduce internal and external coupling between amplifiers.

The CA3048 is supplied in a 16-lead dual-in-line plastic package.

- High input resistance 90 k Ω typ.
- Undistorted output voltage 2 V rms min.
- Output Impedance 1 k Ω typ.
- Open-loop bandwidth 300 kHz typ.

APPLICATIONS

- Multi-channel or cascade operation
- Low-level preamplifiers
- Equalizers
- Linear signal mixers
- Tone generators
- Multivibrators
- AC integrators



92CS-15470R2

Fig. 1 - Block diagram for CA3048.

Linear Integrated Circuits

CA3048

ABSOLUTE-MAXIMUM RATINGS at $T_A = 25^\circ\text{C}$:

DISSIPATION:

At $T_A = 55^\circ\text{C}$ 750 mW
 Above $T_A = 55^\circ\text{C}$ Derate linearly at 7.7 mW/ $^\circ\text{C}$

TEMPERATURE RANGE:

Operating -40°C to $+85^\circ\text{C}$
 Storage -65°C to $+150^\circ\text{C}$

POWER SUPPLY VOLTAGE +16 V

AC INPUT VOLTAGE 0.5 V rms

MAXIMUM VOLTAGE RATINGS

The following chart gives the range of voltages which can be applied to the terminals listed vertically with respect to the terminals listed horizontally. For example, the voltage range between vertical terminal 2 and horizontal terminal 4 is +2 to -3.6 volts.

TERMINAL No.	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
1		+16 0	*	*	*	*	*	*	*	*	*	*	*	*	0 -16	*
2			*	+2 -3.6	0	*	*	+2 -3.6	-3.6	*	*	+16 0	+2 -3.6	*	+16 0	0 -16
3				+5 -5	*	*	*	*	*	*	*	*	*	*	*	*
4					+3.6 -2	*	*	*	*	*	*	*	*	*	*	*
5						0 -16	*	+2 -3.6	+2 -3.6	*	0 -16	+16 0	+2 -3.6	*	+16 0	*
6							*	*	*	*	*	*	0 -16	*	*	*
7								+5 -5	*	*	*	*	*	*	*	*
8									*	*	*	*	*	*	*	*
9										+5 -5	*	*	*	*	*	*
10											*	*	*	*	*	*
11												*	*	*	*	*
12													0 -16	*	*	*
13														+5 -5	*	*
14															*	*
15																+16 0
16																

* Voltages are not normally applied between these terminals. Voltages appearing between these terminals will be safe if the specified limits between all other terminals are not exceeded.

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

CHARACTERISTICS	SYMBOLS	TEST CONDITIONS	TEST CIRCUIT	LIMITS CA3048			UNITS	TYPICAL CHARACTERISTICS CURVES	
			FIG.	MIN.	TYP.	MAX.		FIG.	
STATIC									
Current drain per amplifier pair	I_{12} or I_{15}	$V_{CC} = +12\text{V}$	3	9.5	13.5	17.5	mA	4,5	
DC Voltage at Output Terminals	V_1, V_6, V_{11}, V_{16}	$V_{CC} = +12\text{V}$	3	6.1	6.9	8.1	V	-	
DC Voltage at Feedback Terminals	V_3, V_7, V_{10}, V_{14}	$V_{CC} = +12\text{V}$	3	1.7	2.0	2.3	V	-	
DC Voltage at Input Terminals	V_4, V_8, V_9, V_{13}	$V_{CC} = +12\text{V}$	3	2.2	2.5	2.8	V	-	
DYNAMIC (Characteristics given are for each amplifier with no AC feedback)									
Open-Loop Gain	A_{OL}	$V_{CC} = +12\text{V}$ $E_{IN} = 2\text{mV}$ $f = 10\text{kHz}$	6	53	58	-	dB	7,8	
Output Voltage Swing	$V_{O(\text{rms})}$	$V_{CC} = +12\text{V}$ $f = 1\text{kHz}$ THD = 5%	6	2.0	2.4	-	V	-	
Open-Loop -3dB Bandwidth	BW	$V_{CC} = +12\text{V}$ $E_{IN} = 2\text{mV}$	6	250	300	-	kHz	9	
Total Harmonic Distortion	THD	$V_{CC} = +12\text{V}, f = 1\text{kHz}$ $E_{OUT} = 2\text{V rms}$	6	-	0.65	-	%	10	
Input Resistance	R_{IN}	OPEN LOOP Terminals 3, 7, 10, and 14 are by-passed to ground $f = 1\text{kHz}$	-	-	90	-	$k\Omega$	-	
Input Capacitance	C_{IN}	$f = 1\text{MHz}$	-	-	9	-	pF	-	
Output Resistance	R_{OUT}	Terminals 3, 7, 10 and 14 are by-passed to ground	-	-	1	-	$k\Omega$	-	
Output Capacitance	C_{OUT}	$f = 1\text{MHz}$	-	-	18	-	pF	-	
Feedback Capacitance (Output to non-inverting Input)	C_{FB}	$V_{CC} = +12\text{V}$ $f = 1\text{MHz}$	-	-	<0.1	-	pF	-	
Broad-Band Output Noise Voltage	E_N	$V_{CC} = +12\text{V}$ $R_S = 10\text{k}\Omega$ $A = 40\text{dB}$ Equivalent Noise BW = 50 kHz	11	-	0.3	1	mV	-	
Output Noise Voltage "Weighted"	$E_N(\text{WT})$		12	-	0.5	2.2	mV	-	
Noise Figure	NF ($R_S = 5\text{k}\Omega$)	$f =$	10 Hz	-	-	10	-	dB	-
			100 Hz	-	-	5.8	-	dB	
			1 kHz	-	-	2	-	dB	
			10 kHz	-	-	1.1	-	dB	
			100 kHz	-	-	0.6	-	dB	
Inter-Amplifier Audio Separation "Cross Talk"		$V_{CC} = +12\text{V}$ $f = 1\text{kHz}$ 0 dB = 0.78V	13	-	<-45	-	dB	-	
Inter-Amplifier Capacitance (Any amplifier output to any other amplifier input)	C	$V_{CC} = +12\text{V}$ $f = 1\text{MHz}$	-	-	<0.02	-	pF	-	

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CA3048

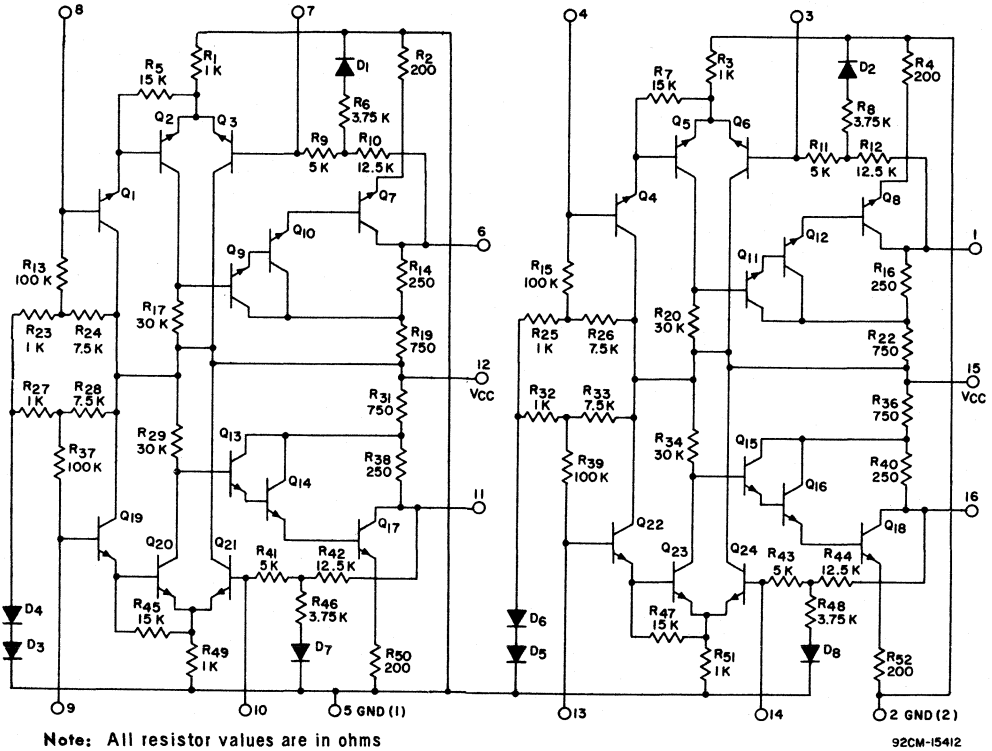


Fig.2 - Schematic diagram for CA3048.

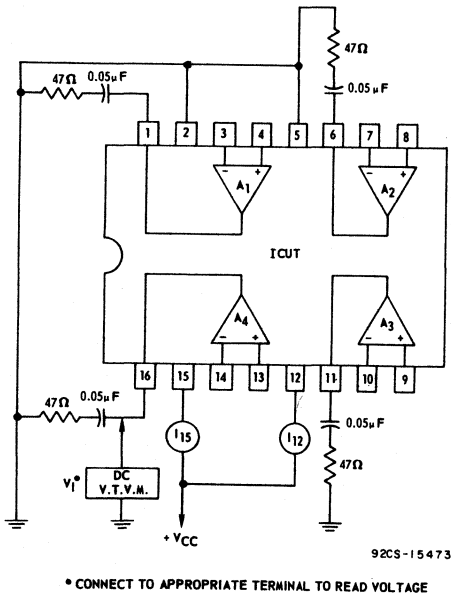


Fig.3 - Test circuit for measurement of collector supply voltage and currents.

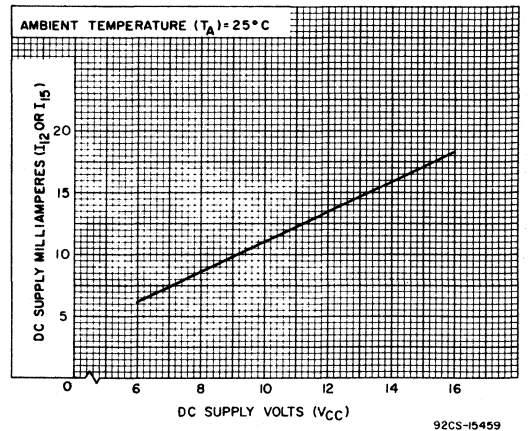


Fig.4 - Typical DC supply current vs supply voltage.

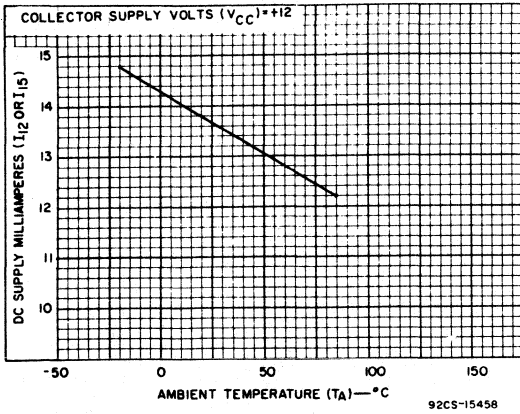


Fig. 5 - Typical DC supply current vs ambient temperature.

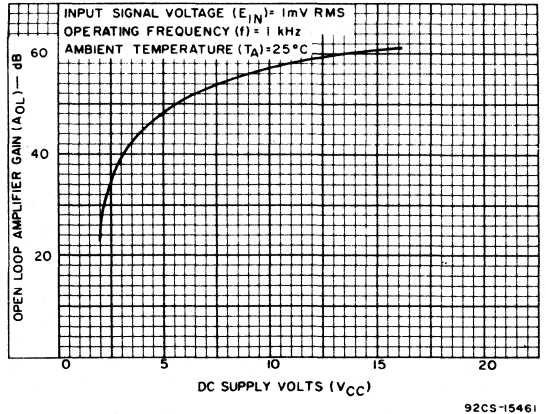
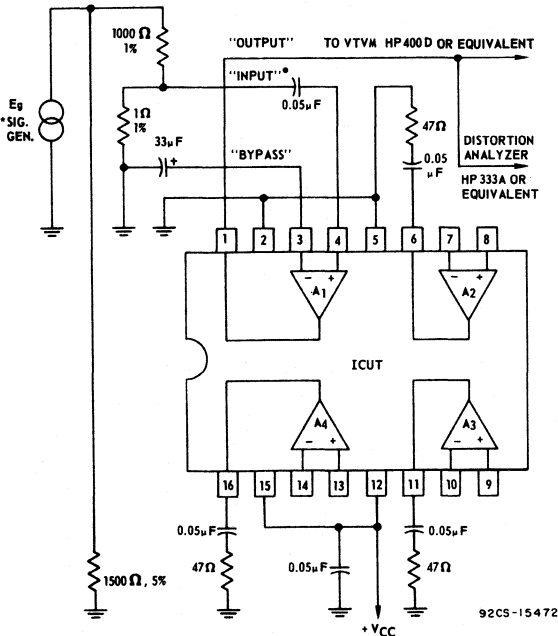


Fig. 7 - Typical amplifier gain vs DC supply voltage.



* Sig Gen should be a low distortion type (0.2% THD or less) HP206A or equivalent.

● Adjustment of E_g to 2 volts will make $E_s = 2mV$.

Test Circuit shows Amplifier #1 under test, to test Amplifiers 2, 3, or 4; Connect terminals as shown in Table.

AMPLIFIER	TERMINALS		
	OUTPUT	INPUT	BYPASS
1	1	4	3
2	6	8	7
3	11	9	10
4	16	13	14

Fig. 6 - Test circuit for measurement of distortion, open-loop gain and bandwidth characteristics.

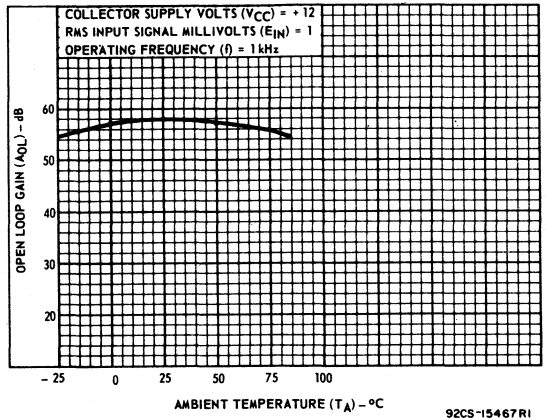


Fig. 8 - Typical open-loop gain vs ambient temperature.

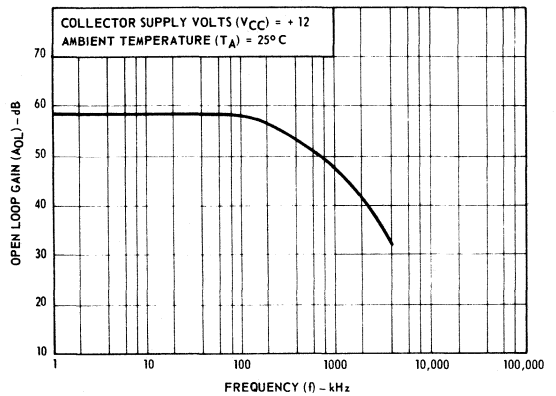


Fig. 9 - Typical open-loop gain vs frequency.

Linear Integrated Circuits

CA3048

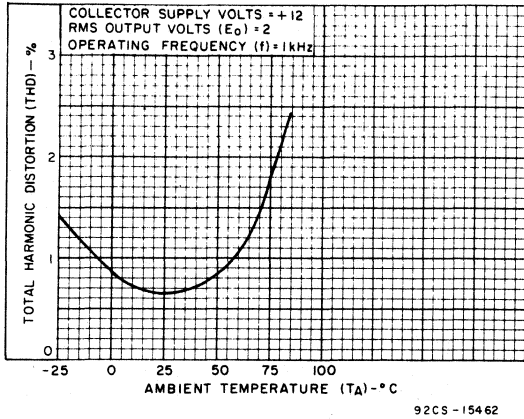
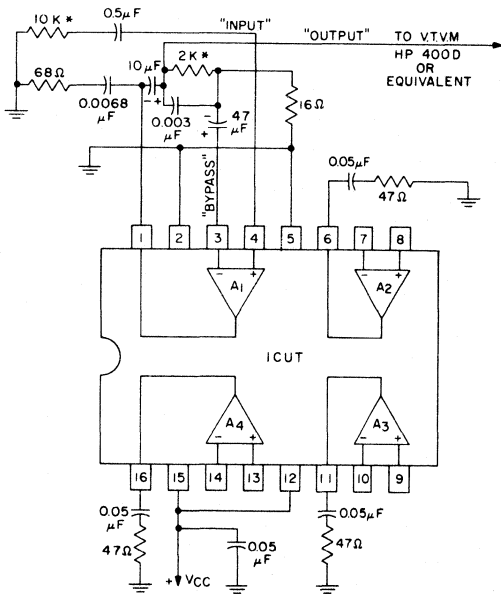


Fig.10 - Typical total harmonic distortion vs ambient temperature.



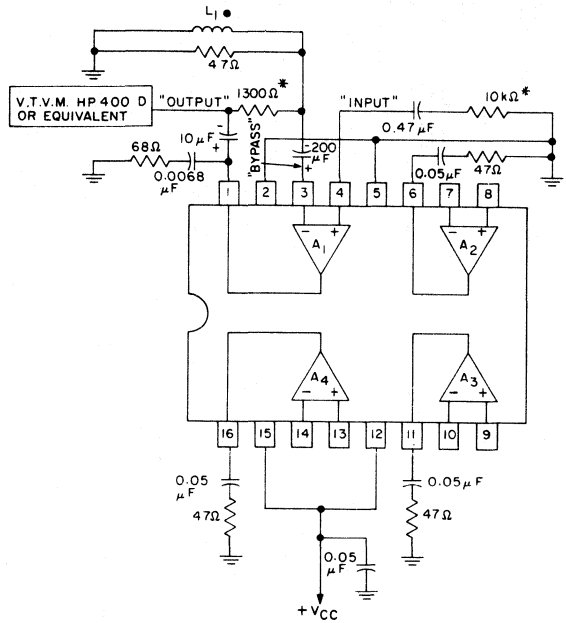
* RESISTORS ARE METALFILM TYPE, 1%

92CS-15465

To test Amplifiers 1, 2, 3, or 4, connect terminals as shown in Table.

AMPLIFIER	TERMINALS		
	OUTPUT	INPUT	BYPASS
1	1	4	3
2	6	8	7
3	11	9	10
4	16	13	14

Fig.11 - Test circuit for measurement of broadband noise characteristic.



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● L₁ - 2.5 millihenry inductor, dc resistance 0.3 ohms or less.

* Resistors metal film type, 1%. To test amplifiers, connect terminals as shown in Table.

AMPLIFIER	TERMINALS		
	OUTPUT	INPUT	BYPASS
1	1	4	3
2	6	8	7
3	11	9	10
4	16	13	14

Fig.12 - Test circuit for measurement of "weighted" output noise voltage characteristic.

OPERATING CONSIDERATIONS

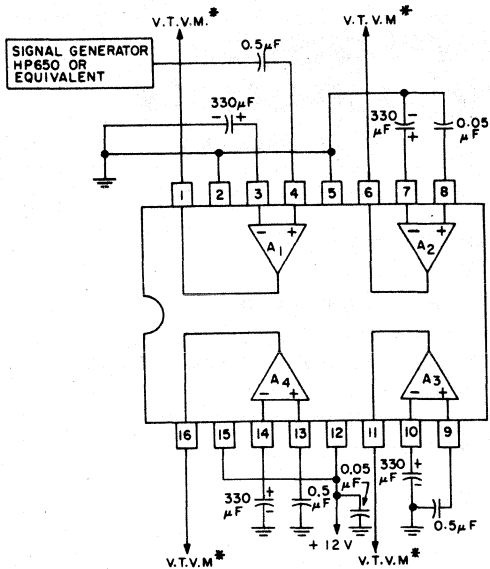
Economical Gain Control

The CA3048 is designed to permit flexibility in the methods by which amplifier gain can be controlled. Fig.14 shows a curve of the gain of an amplifier when the internal resistive feedback of the device is used in conjunction with an external resistor. Although measured gain of various amplifiers will not be uniform, because of tolerances of internal resistances, this method is very economical and easy to apply.

Stability

The CA3048, as in other devices having high gain-bandwidth product, requires some attention to circuit layout, design, and construction to achieve stability.

Should the CA3048 be left unterminated, socket capacitance alone will provide sufficient feedback to cause high frequency oscillations; therefore, all test circuits in this data bulletin include loading networks that provide stability under all conditions.



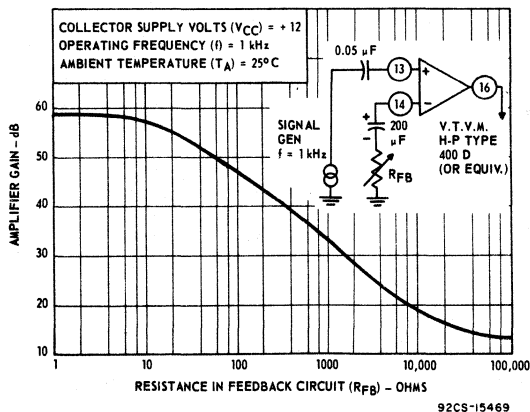
92CS-15471

* V.T.V.M. - Hewlett-Packard Model 400D or equivalent.

Procedure:

1. Adjust Signal Generator for 0 dB output at reference terminal.
2. Read voltage at other output terminals (Figure shows terminal #1 used as reference).

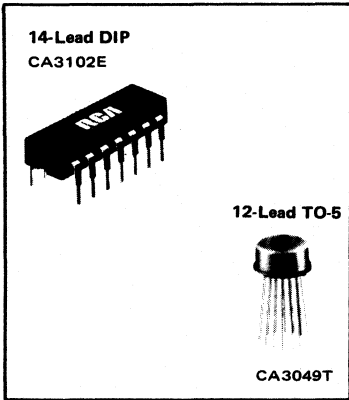
Fig.13 - Test circuit for measurement of inter-amplifier audio separation "cross talk" characteristic.



92CS-15469

Fig.14 - Typical amplifier gain vs feedback resistance.

CA3049T, CA3102E



DUAL HIGH-FREQUENCY DIFFERENTIAL AMPLIFIERS

For Low-Power Applications at Frequencies up to 500 MHz

Features:

- Power Gain 23 dB (typ.) at 200 MHz
- Noise Figure 4.6 dB (typ.) at 200 MHz
- Two differential amplifiers on a common substrate
- Independently accessible inputs and outputs
- Full military-temperature-range capability- (-55°C to $+125^{\circ}\text{C}$) for the CA3102E and for the CA3049T

RCA-CA3049T and CA3102E* consist of two independent differential amplifiers with associated constant-current transistors on a common monolithic substrate. The six transistors which comprise the amplifiers are general-purpose devices which exhibit low $1/f$ noise and a value of f_T in excess of 1 GHz. These features make the CA3049T and CA3102E useful from dc to 500 MHz. Bias and load resistors have been omitted to provide maximum application flexibility.

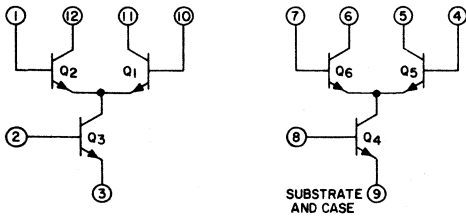
The monolithic construction of the CA3049T and CA3102E provides close electrical and thermal matching of the amplifiers. This feature makes these devices particularly useful in dual-channel applications where matched performance of the two channels is required.

The CA3102E is like the CA3049T except that it has a separate substrate connection for greater design flexibility. The CA3049T is supplied in the 12-lead TO-5 package; the CA3102E, in the 14-lead plastic dual-in-line package.

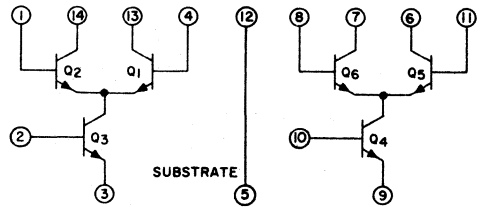
Applications

- VHF amplifiers
- VHF mixers
- Multifunction combinations — RF/Mixer/Oscillator; Converter/IF
- IF amplifiers (differential and/or cascode)
- Product detectors
- Doubly balanced modulators and demodulators
- Balanced quadrature detectors
- Cascade limiters
- Synchronous detectors
- Balanced mixers
- Synthesizers
- Balanced (push-pull) cascode amplifiers
- Sense amplifiers

*Formerly Developmental No. TA6228.



Schematic Diagram for CA3049T



Schematic Diagram for CA3102E

CA3049T, CA3102E

MAXIMUM RATINGS, ABSOLUTE-MAXIMUM VALUES,
AT $T_A = 25^\circ\text{C}$

Power Dissipation, P:	CA3049T	CA3102E
Any one transistor	300	300 mW
Total package	600	750 mW
For $T_A > 55^\circ\text{C}$ Derate at:	5	6.67 mW/ $^\circ\text{C}$
Temperature Range:		
Operating	-55 to + 125	-55 to + 125 $^\circ\text{C}$
Storage	-65 to + 150	-65 to + 150 $^\circ\text{C}$

The following ratings apply for each transistor in the devices

Collector-to-Emitter Voltage, V_{CEO}	15	V
Collector-to-Base Voltage, V_{CBO}	20	V
Collector-to-Substrate Voltage, V_{CIO}^*	20	V
Emitter-to-Base Voltage, V_{EBO}	5	V
Collector Current, I_C	50	mA

*The collector of each transistor of the CA3049T and CA3102E is isolated from the substrate by an integral diode. The substrate (terminal 9) must be connected to the most negative point in the external circuit to maintain isolation between transistors and to provide for normal transistor action.

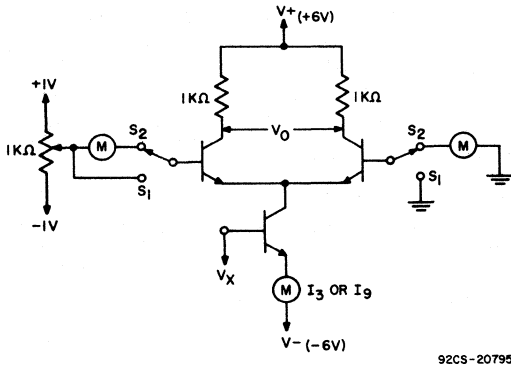
ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

CHARACTERISTICS	SYMBOLS	TEST CONDITIONS	TEST CIRCUIT	CA3102E LIMITS			CA3049T LIMITS			UNITS	TYPICAL CHARACTERISTICS CURVES FIG.
				FIG.	MIN.	TYP.	MAX.	MIN.	TYP.		
STATIC CHARACTERISTICS											
For Each Differential Amplifier											
Input Offset Voltage	V_{IO}		1	---	0.25	5	---	0.25	---	mV	-4
Input Offset Current	I_{IO}	$I_3 = I_9 = 2\text{ mA}$	1	---	0.3	3	---	0.3	---	μA	---
Input Bias Current	I_{IB}		1	---	13.5	33	---	13.5	33	μA	5
Temperature Coefficient Magnitude of Input-Offset Voltage	$ \Delta V_{IO} /\Delta T$		1	---	1.1	---	---	1.1	---	$\mu\text{V}/^\circ\text{C}$	4
For Each Transistor											
DC Forward Base-to-Emitter Voltage	V_{BE}	$V_{CE} = 6\text{ V}$ $I_C = 1\text{ mA}$	---	674	774	874	---	774	---	mV	6
Temperature Coefficient of Base-to-Emitter Voltage	$\Delta V_{BE}/\Delta T$	$V_{CE} = 6\text{ V}$, $I_C = 1\text{ mA}$	---	---	-0.9	---	---	-0.9	---	$\text{mV}/^\circ\text{C}$	6
Collector-Cutoff Current	I_{CBO}	$V_{CB} = 10\text{ V}$, $I_E = 0$	---	---	0.0013	100	---	0.0013	100	nA	7
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 1\text{ mA}$, $I_B = 0$	---	15	24	---	15	24	---	V	---
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 10\text{ }\mu\text{A}$, $I_E = 0$	---	20	60	---	20	60	---	V	---
Collector-to-Substrate Breakdown Voltage	$V_{(BR)CIO}$	$I_C = 10\text{ }\mu\text{A}$, $I_B = 0$, $I_E = 0$	---	20	60	---	20	60	---	V	---
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 10\text{ }\mu\text{A}$, $I_C = 0$	---	5	7	---	5	7	---	V	---
DYNAMIC CHARACTERISTICS											
1/f Noise Figure (For Single Transistor)	NF	$f = 100\text{ KHz}$, $R_S = 500\text{ }\Omega$ $I_C = 1\text{ mA}$	---	---	1.5	---	---	1.5	---	dB	12
Gain-Bandwidth Product (For Single Transistor)	f_T	$V_{CE} = 6\text{ V}$, $I_C = 5\text{ mA}$	---	---	1.35	---	---	1.35	---	GHz	11
Collector-Base Capacitance	C_{CB}	$I_C = 0$ $V_{CB} = 5\text{ V}$	*	---	0.28	---	---	0.28	---	pF	8
Collector-Substrate Capacitance	C_{CI}	$I_C = 0$ $V_{CI} = 5\text{ V}$	**	---	0.15	---	---	0.28	---	pF	8
For Each Differential Amplifier											
Common-Mode Rejection Ratio	CMR	$I_3 = I_9 = 2\text{ mA}$	---	---	100	---	---	100	---	dB	---
AGC Range, One Stage	AGC	Bias Voltage = -6V	2	---	75	---	---	75	---	dB	---
Voltage Gain, Single-Ended Output	A	Bias Voltage = -4.2V $f = 10\text{ MHz}$	2	18	22	---	---	22	---	dB	9, 10
Insertion Power Gain	G_p	$f = 200\text{ MHz}$	Cascode	3	---	23	---	23	---	dB	---
Noise Figure	NF	$V_{CC} = 12\text{ V}$	Cascode	3	---	4.6	---	4.6	---	dB	---
Input Admittance	Y_{11}	For Cascode Configuration $I_3 = I_9 = 2\text{ mA}$	Cascode	---	---	$1.5 + j 2.45$	---	$1.5 + j 2.45$	---	mmho	14, 16, 18
			Diff. Amp.	---	---	$0.878 + j 1.3$	---	$0.878 + j 1.3$	---	mmho	15, 17, 19
Reverse Transfer Admittance	Y_{12}	For Diff. Amplifier Configuration $I_3 = I_9 = 4\text{ mA}$	Cascode	---	---	$0 - j 0.008$	---	$0 - j 0.008$	---	mmho	---
			Diff. Amp.	---	---	$0 - j 0.013$	---	$0 - j 0.013$	---	mmho	---
Forward Transfer Admittance	Y_{21}	(each collector $I_C \approx 2\text{ mA}$)	Cascode	---	---	$17.9 - j 30.7$	---	$17.9 - j 30.7$	---	mmho	26, 28, 30
			Diff. Amp.	---	---	$-10.5 + j 13$	---	$-10.5 + j 13$	---	mmho	27, 29, 31
Output Admittance	Y_{22}		Cascode	---	---	$-0.503 - j 15$	---	$-0.503 - j 15$	---	mmho	20, 22, 24
			Diff. Amp.	---	---	$0.071 + j 0.62$	---	$0.071 + j 0.62$	---	mmho	21, 23, 25

* Terminals 1 & 14, or 7 & 8. (CA3102E) 1 & 12 or 6 & 7 (CA3049T)
 ** Terminals 13 & 4, or 6 & 11. (CA3102E) 10 & 11 or 4 & 5 (CA3049T)

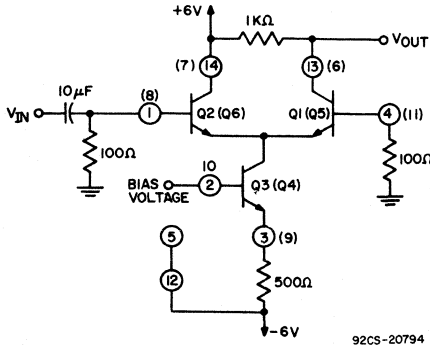
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CA3049T, CA3102E



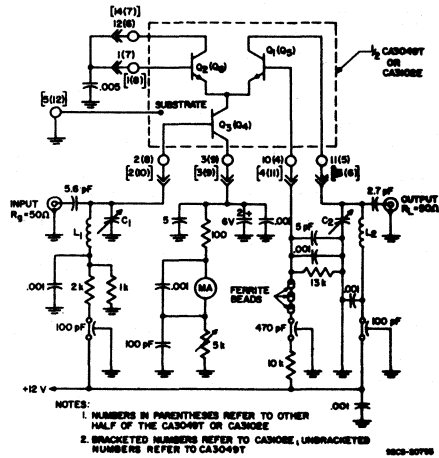
92CS-20795

Fig. 1—Static characteristics test circuit for CA3102E.



92CS-20794

Fig. 2—AGC range and voltage gain test circuit for CA3102E.

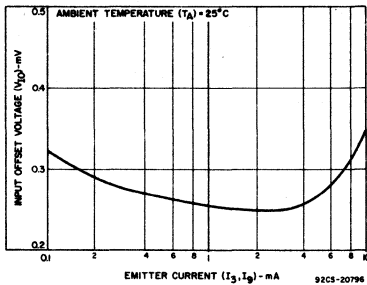


92CS-20796

L₁, L₂ — Approx. 1/2 Turn #18 Tinned Copper Wire, 5/8" Dia.
 C₁, C₂ — 15 pF Variable Capacitors (Hammarlund, MAC-15; or Equivalent)
 All Capacitors in μF Unless Otherwise Indicated
 All Resistors in Ohms Unless Otherwise Indicated

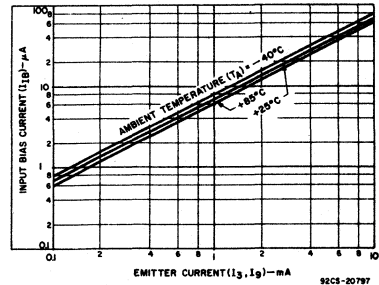
Fig. 3—200 MHz cascode power gain and noise figure test circuit.

Typical Characteristics for CA3049T and CA3102E



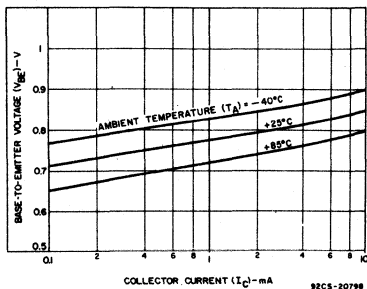
92CS-20798

Fig. 4—Input offset voltage vs. emitter current.



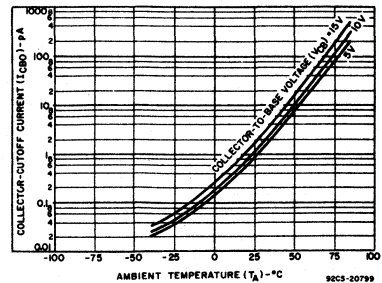
92CS-20787

Fig. 5—Input bias current vs. emitter current.



92CS-20798

Fig. 6—Base-to-emitter voltage vs. collector current.



92CS-20799

Fig. 7—Collector-cutoff current vs. temperature.

Typical Characteristics for CA3049T and CA3102E (cont'd)

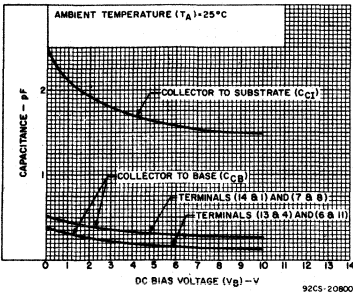


Fig. 8—Capacitance vs. dc bias voltage.

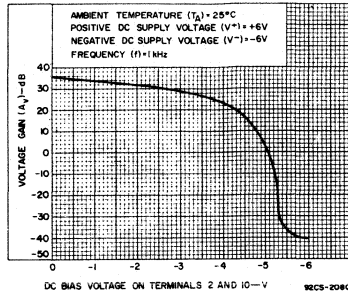


Fig. 9—Voltage gain vs. dc bias voltage.

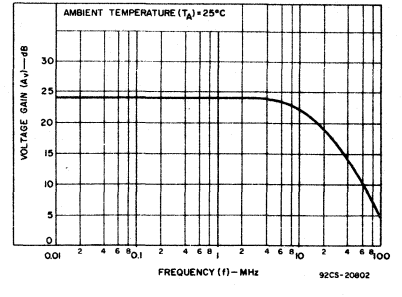


Fig. 10—Voltage gain vs. frequency.

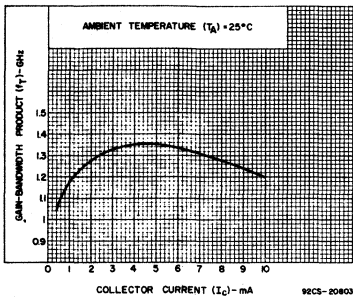


Fig. 11—Gain-bandwidth product vs. collector current.

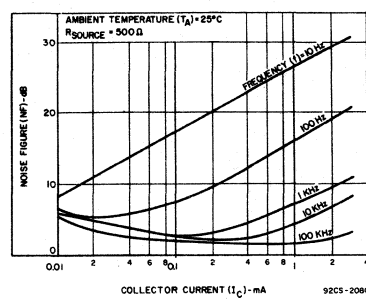


Fig. 12—1/f noise figure vs. collector current.

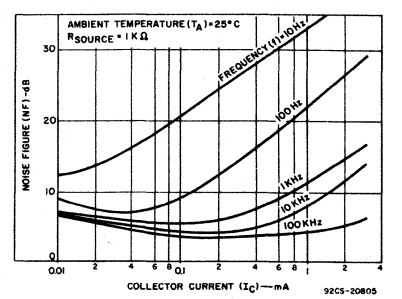


Fig. 13—1/f noise figure vs. collector current.

Typical Input Admittance Characteristics for CA3049T and CA3102

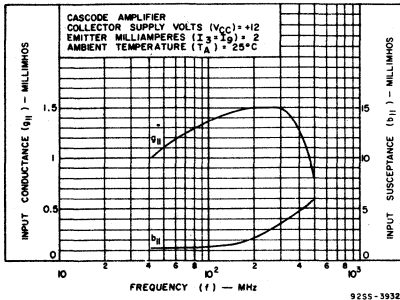


Fig. 14—Input admittance (Y_{11}) vs. frequency.

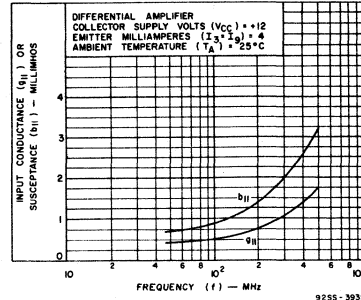


Fig. 15—Input admittance (Y_{11}) vs. frequency.

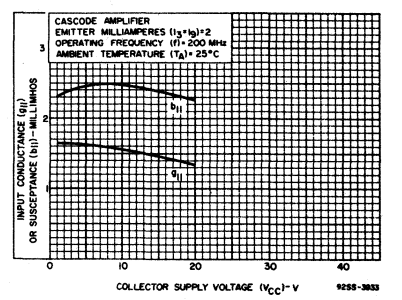


Fig. 16—Input admittance (Y_{11}) vs. collector supply voltage.

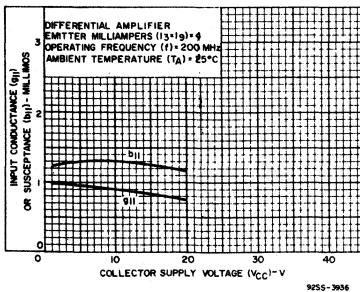


Fig. 17—Input admittance (Y_{11}) vs. collector supply voltage.

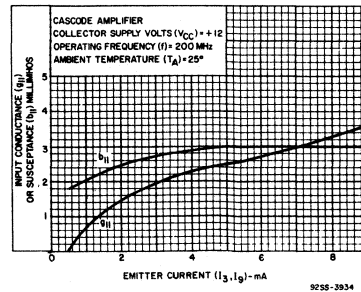


Fig. 18—Input admittance (Y_{11}) vs. emitter current.

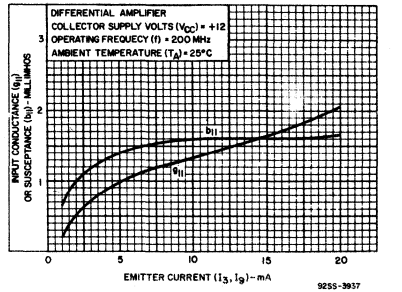


Fig. 19—Input admittance (Y_{11}) vs. emitter current.

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CA3049T, CA3102E

Typical Output Admittance Characteristics for CA3049T and CA3102E

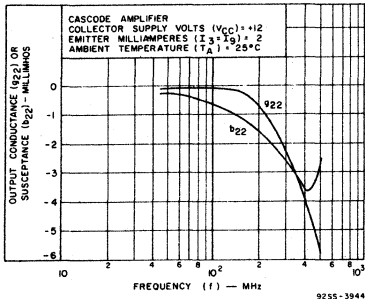


Fig. 20—Output admittance (Y_{22}) vs. frequency.

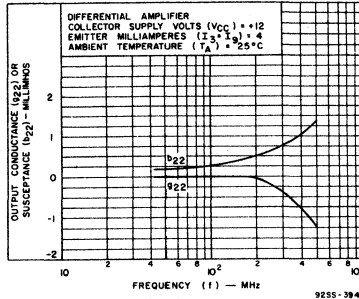


Fig. 21—Output admittance (Y_{22}) vs. frequency.

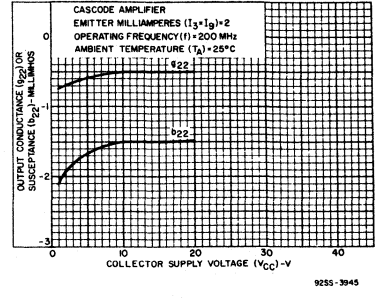


Fig. 22—Output admittance (Y_{22}) vs. collector supply voltage.

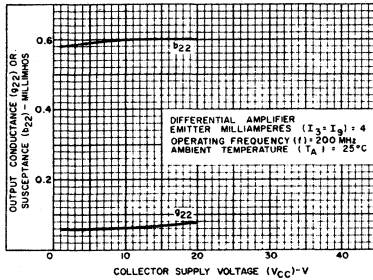


Fig. 23—Output admittance (Y_{22}) vs. collector supply voltage.

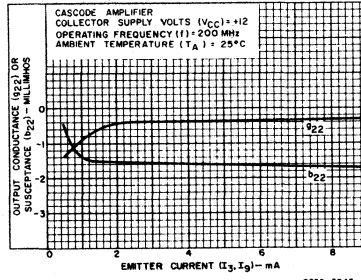


Fig. 24—Output admittance (Y_{22}) vs. emitter current.

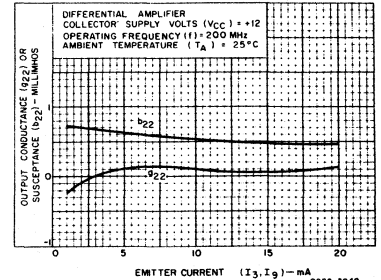


Fig. 25—Output admittance (Y_{22}) vs. emitter current.

Typical Forward Transfer Characteristics for CA3049T and CA3102E

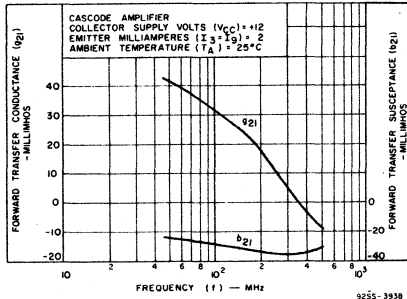


Fig. 26—Forward transfer admittance (Y_{21}) vs. frequency.

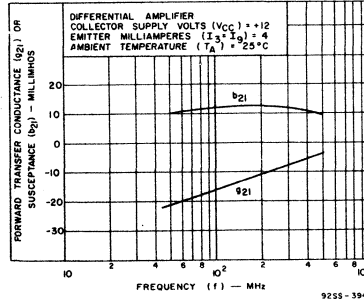


Fig. 27—Forward transfer admittance (Y_{21}) vs. frequency.

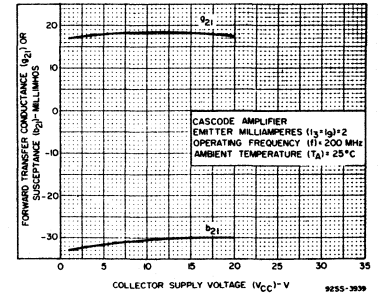


Fig. 28—Forward transfer admittance (Y_{21}) vs. collector supply voltage.

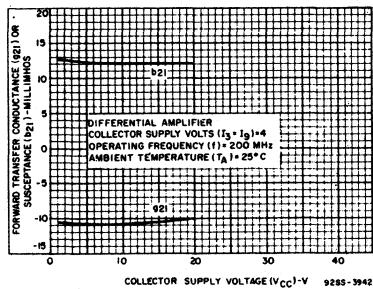


Fig. 29—Forward transfer admittance (Y_{21}) vs. collector supply voltage.

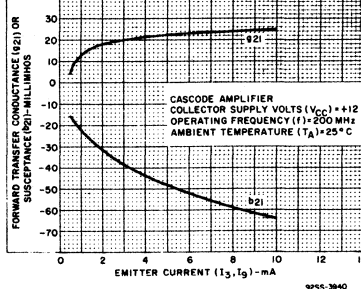


Fig. 30—Forward transfer admittance (Y_{21}) vs. emitter current.

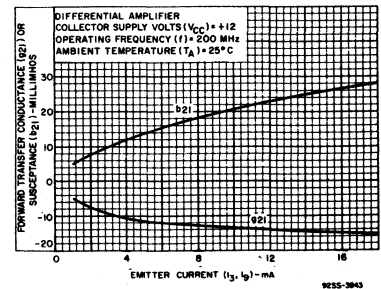
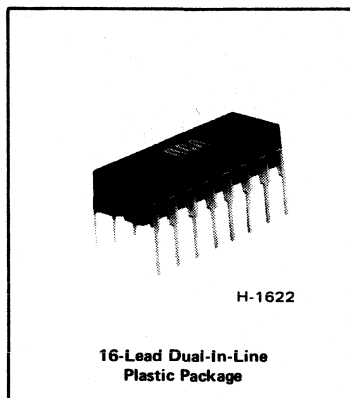


Fig. 31—Forward transfer admittance (Y_{21}) vs. emitter current.



Four Independent AC Amplifiers

Special-Function Sub-System for Stereo Preamplifiers, Magnetic Pickups, Tape Heads, etc.

Features:

- Four AC amplifiers on a common substrate
- Independently accessible inputs and outputs
- Operates from single-ended supply

EACH AMPLIFIER

- High voltage gain - 53 dB min.
- High input resistance - 90 k Ω typ.
- Undistorted output voltage - 2 V rms min.

- Output impedance - 1 k Ω typ.
- Open-loop bandwidth - 300 kHz typ.

Applications:

- Full-function stereo preamplifiers
- Tape recorder and playback preamplifiers
- Tone generators

The RCA-CA3052 is a silicon monolithic integrated circuit designed specifically for stereo preamplifier service. The circuit consists of four independent ac amplifiers which can operate from a single-ended supply.

The CA3052 can operate as an equalizer amplifier in tape recorders, magnetic cartridge phonograph applications, and tone control amplifiers. It can provide all of the amplification necessary for a full-function stereo preamplifier.

The CA3052 is supplied in a 16-lead dual-in-line plastic package.

RCA-CA3052 is schematically identical with the CA3048 Amplifier Array (File No. 377). Each amplifier of the CA3048 is tightly specified for equivalent output noise under a variety of test methods. The CA3052 is specified using RIAA test methods for equivalent input noise using one test method for amplifiers 1 and 4, and an appropriately different method for amplifiers 2 and 3.

ABSOLUTE-MAXIMUM RATING at $T_A = 25^\circ\text{C}$:

DISSIPATION:

Up to $T_A = 55^\circ\text{C}$	750 mW
Above $T_A = 55^\circ\text{C}$	Derate linearly at 7.7 mW/ $^\circ\text{C}$

TEMPERATURE RANGE:

Operating	-40°C to $+85^\circ\text{C}$
Storage	-65°C to $+150^\circ\text{C}$

LEAD TEMPERATURE (During Soldering):

At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm)	$+265^\circ\text{C}$
from case for 10 seconds max.	

POWER SUPPLY VOLTAGE +16 V

AC INPUT VOLTAGE 0.5 V rms

Linear Integrated Circuits

CA3052

MAXIMUM VOLTAGE RATINGS

The following chart gives the range of voltages which can be applied to the terminals listed vertically with respect to the terminals listed horizontally. For example, the voltage range between vertical terminal 2 and horizontal terminal 4 is +2 to -3.6 volts.

TERMINAL No.	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
1		+16 0	*	*	*	*	*	*	*	*	*	*	*	*	0 -16	*
2			*	+2 -3.6	0	*	*	+2 -3.6	+2 -3.6	*	*	+16 0	+2 -3.6	*	+16 0	0 -16
3				+5 -5	*	*	*	*	*	*	*	*	*	*	*	*
4					+3.6 -2	*	*	*	*	*	*	*	*	*	*	*
5						0 -16	*	+2 -3.6	+2 -3.6	*	0 -16	+16 0	+2 -3.6	*	+16 0	*
6							*	*	*	*	*	*	0 -16	*	*	*
7								+5 -5	*	*	*	*	*	*	*	*
8									*	*	*	*	*	*	*	*
9										+5 -5	*	*	*	*	*	*
10											*	*	*	*	*	*
11												*	*	*	*	*
12													0 -16	*	*	*
13														+5 -5	*	*
14															*	*
15																+16 0
16																

* Voltages are not normally applied between these terminals. Voltages appearing between these terminals will be safe if the specified limits between all other terminals are not exceeded.

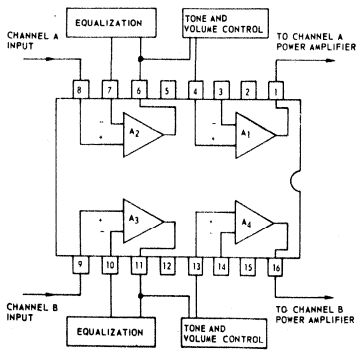


Fig. 1 - Block diagram of stereo preamplifier using CA3052.

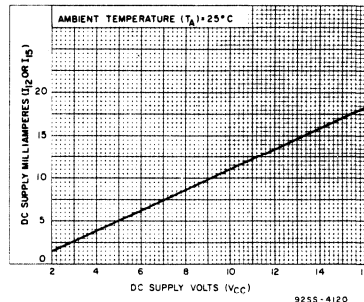


Fig. 2 - Typical DC supply current vs supply voltage.

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

CHARACTERISTICS	SYMBOLS	TEST CONDITIONS	LIMITS CA3052			UNITS
			MIN.	TYP.	MAX.	
STATIC						
Current drain per amplifier pair	I_{12} or I_{15}	$V_{CC} = +12\text{ V}$	9.5	13.5	17.5	mA
DC Voltage at Output Terminals	$V_1, V_6,$ V_{11}, V_{16}	$V_{CC} = +12\text{ V}$	6.1	6.9	8.1	V
DC Voltage at Feedback Terminals	$V_3, V_7,$ V_{10}, V_{14}	$V_{CC} = +12\text{ V}$	1.7	2.0	2.3	V
DC Voltage at Input Terminals	$V_4, V_8,$ V_9, V_{13}	$V_{CC} = +12\text{ V}$	2.2	2.5	2.8	V
DYNAMIC each amplifier with no AC feedback unless otherwise noted—terminals 3, 7, 10, & 14 bypassed to ground						
Open-Loop Gain	A_{OL}	$V_{CC} = +12\text{ V}$ $E_{IN} = 2\text{ mV}$ $f = 10\text{ kHz}$	53	58	—	dB
Open-Loop Output Voltage Swing	$V_O(\text{rms})$	$V_{CC} = +12\text{ V}$ $f = 1\text{ kHz}$ THD = 5%	2.0	2.4	—	V
Open-Loop -3 dB Bandwidth	BW	$V_{CC} = +12\text{ V}$ $E_{IN} = 2\text{ mV}$	—	300	—	kHz
Open-Loop Total Harmonic Distortion	THD	$V_{CC} = +12\text{ V}, f = 1\text{ kHz}$ $E_{OUT} = 2\text{ V rms}$	—	0.65	—	%
Input Resistance	R_I	$V_{CC} = +12\text{ V}, f = 1\text{ kHz}$	—	90	—	$k\Omega$
Input Capacitance	C_I	$V_{CC} = +12\text{ V}, f = 1\text{ MHz}$	—	9	—	pF
Output Resistance	R_O	$V_{CC} = +12\text{ V}, f = 1\text{ kHz}$	—	1	—	$k\Omega$
Feedback Capacitance (Output to non-inverting Input)	C_{FB}	$V_{CC} = +12\text{ V}$ $f = 1\text{ MHz}$	—	< 0.1	—	pF
Equivalent Input Noise Voltage (Amplifiers 1 & 4), "C" Filter at Output*	$E_{N1}\ddagger$	$V_{CC} = +10\text{ V}$ $R_S = 5\text{ k}\Omega$ $A = 45\text{ dB}$	—	1.7	6.4	μV
Equivalent Input Noise Voltage (Amplifiers 2 & 3) RIAA Compensated*	$E_{N2}\ddagger$	$V_{CC} = +10\text{ V}$ $R_S = 5\text{ k}\Omega$ $A = 64\text{ dB (1 kHz)}$	—	4	15.0	μV
Inter-Amplifier Audio Separation "Cross Talk" ¹¹		$V_{CC} = +12\text{ V}$ $f = 1\text{ kHz}$ 0 dB = 0.78 V	—	< -45	—	dB
Inter-Amplifier Capacitance (Any amplifier output to any other amplifier input)	C	$V_{CC} = +12\text{ V}$ $f = 1\text{ MHz}$	—	< 0.02	—	pF

*Per IHF Standard Methods of Measurement for Audio Amplifiers IHF-A-201, 1966

‡ ac feedback included in test circuit

Linear Integrated Circuits

CA3052

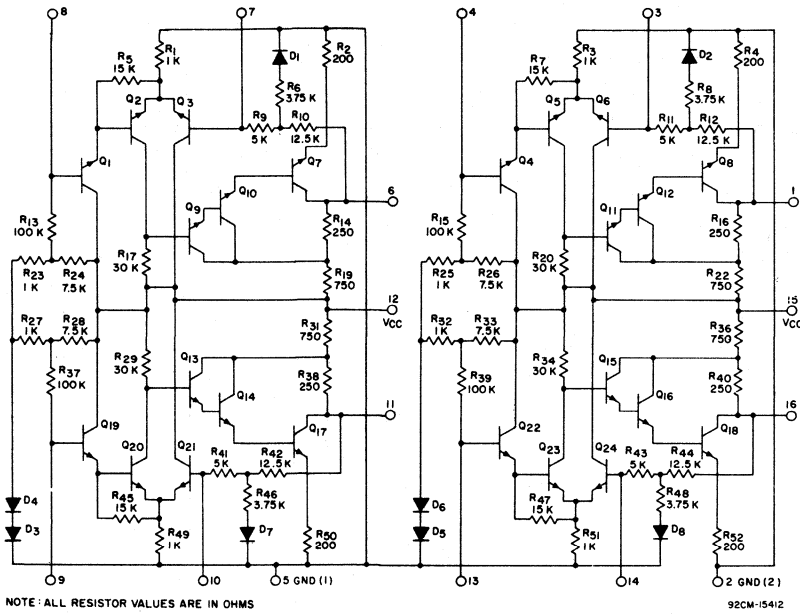


Fig. 3 - Schematic diagram for CA3052.

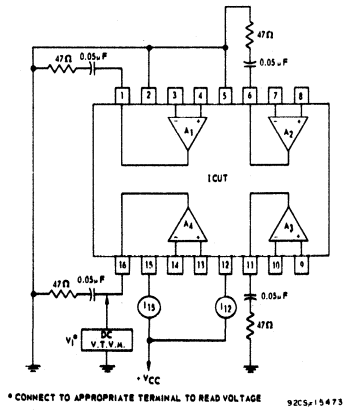


Fig. 4 - Test circuit for measurement of collector supply voltage and currents.

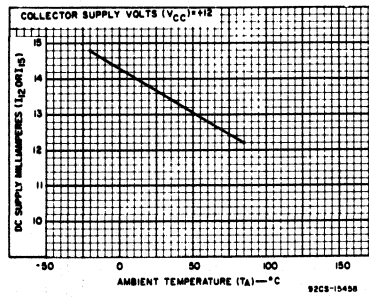
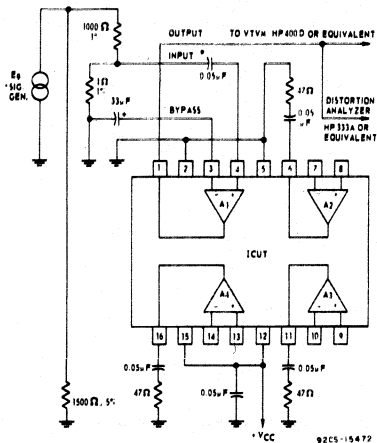


Fig. 5 - Typical DC supply current vs ambient temperature.



* Sig. Gen should be a low distortion type (0.2% THD or less) HP206A or equivalent.
 • Adjustment of E_g to 2 volts will make $E_s = 2\text{mV}$.
 Test Circuit shows Amplifier #1 under test, to test Amplifiers 2, 3, or 4; Connect terminals as shown in Table.

AMPLIFIER	TERMINALS		
	OUTPUT	INPUT	BYPASS
1	1	4	3
2	6	8	7
3	11	9	10
4	16	13	14

Fig. 6 – Test circuit for measurement of distortion, open-loop gain, and bandwidth characteristics.

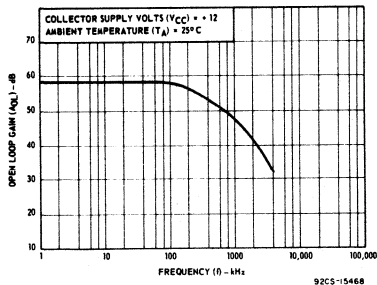


Fig. 9 – Typical open-loop gain vs frequency.

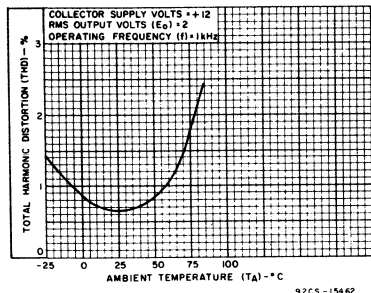


Fig. 10 – Typical total harmonic distortion vs ambient temperature.

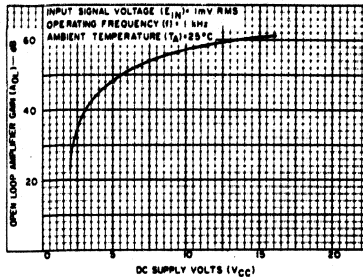


Fig. 7 – Typical amplifier gain vs DC supply voltage.

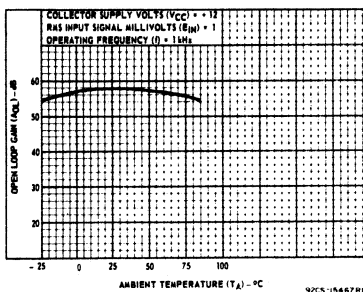
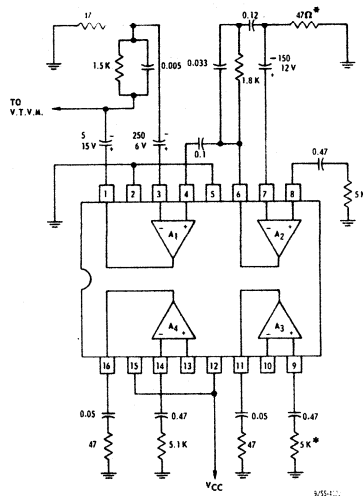
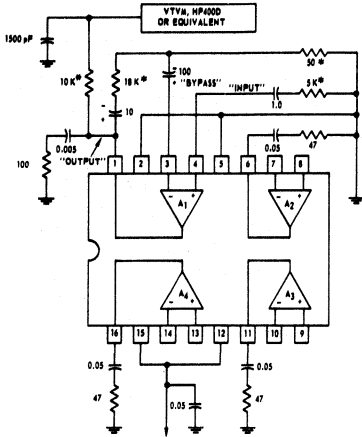


Fig. 8 – Typical open-loop gain vs ambient temperature.



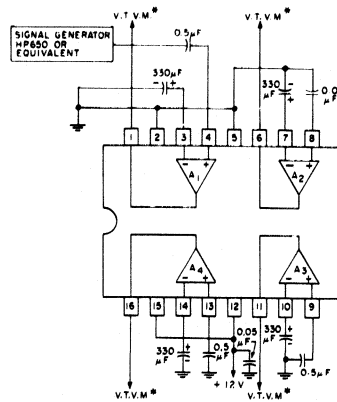
*Resistors are low noise precision (1%) Metal Film type.

Fig. 11 – Test circuit for equivalent input noise voltage measurement, RIAA compensated.



*Resistors are low noise precision, (1%) Metal Film type. Resistor values are in ohms; capacitance values are in microfarads, unless otherwise specified.

Fig. 12— Test circuit for measurement of equivalent input noise voltage of amplifiers 1 and 4.

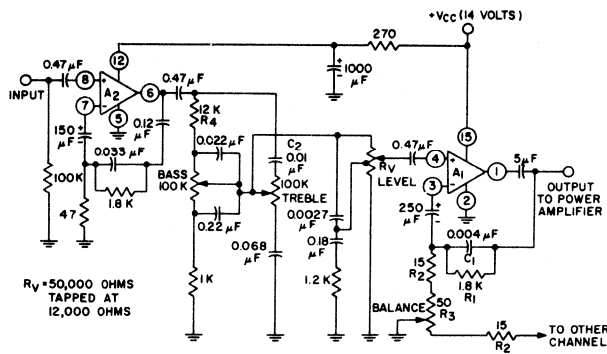


*V.T.V.M. - Hewlett-Packard Model 400D or equivalent.

Procedure:

1. Adjust Signal Generator for 0 dB output at reference terminal.
2. Read voltage at other output terminals (Figure shows terminal #1 used as reference).

Fig. 13 - Test circuit for measurement of inter-amplifier audio separation "cross talk" characteristic.



Performance Data

Gain at 1-kHz reference	47 dB
Boost at 100 Hz	11.5 dB
Boost at 10 kHz	11.5 dB
Cut at 100 Hz	10 dB
Cut at 10 kHz	9 dB

Noise:

- At maximum volume (input shorted) > 70 dB below 1 volt
- At minimum volume > 80 dB below 1 volt

Total harmonic distortion (at 1-kHz reference and an output of 1 volt) < 0.3 per cent

92CM-29305

Fig. 14 - Schematic of one channel of a complete stereo preamplifier.

OPERATING CONSIDERATIONS

Economical Gain Control

The CA3052 is designed to permit flexibility in the methods by which amplifier gain can be controlled. Fig. 15 shows a curve of the gain of an amplifier when the internal resistive feedback of the device is used in conjunction with an external resistor. Although measured gain of various amplifiers will not be uniform, because of tolerances of internal resistances, this method is very economical and easy to apply.

Stability

The CA3052, as in other devices having high gain-band-width product, requires some attention to circuit layout, design, and construction to achieve stability.

Should the CA3052 be left unterminated, socket capacitance alone will provide sufficient feedback to cause high frequency oscillations; therefore, all test circuits in this data bulletin include loading networks that provide stability under all conditions.

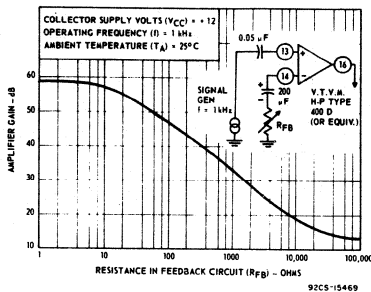
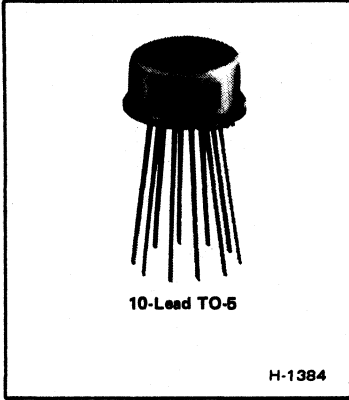


Fig. 15 – Typical amplifier gain vs feedback resistance.

CA3019



Ultra-Fast Low-Capacitance Matched Diodes

For Applications in Communications and Switching Systems

Features:

- Excellent diode match
- Low leakage current
- Low pedestal voltage when gating
- Companion Application Note, ICAN-5299: "Application of the RCA-CA3019 Integrated-Circuit Diode Array"

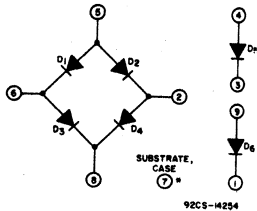
Applications:

- Modulator
- Mixer
- Balanced modulator
- Analog switch
- Diode gate for chopper-modulator applications

The RCA-CA3019 consists of six ultra-fast, low capacitance diodes on a common monolithic substrate. Integrated circuit construction assures excellent static and dynamic matching of the diodes, making the array extremely useful for a wide variety of applications in communication and switching systems.

Four of the diodes are internally connected as a "quad" and two are independently accessible. The substrate is internally connected to the 10-lead TO-5-style case.

For applications such as balanced modulators or ring modulators where capacitive balance is important, the substrate should be returned to a DC potential which is significantly more negative (with respect to the active diodes) than the peak signal applied.



* Connect to most negative circuit potential.

Fig. 1 — Schematic Diagram.

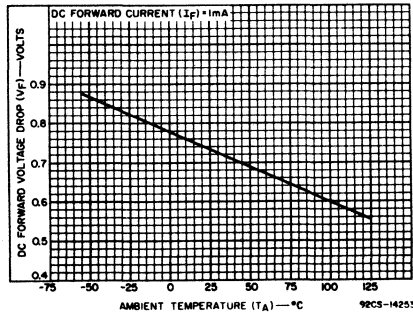


Fig. 2 — DC forward voltage drop (any diode) as a function of temperature.

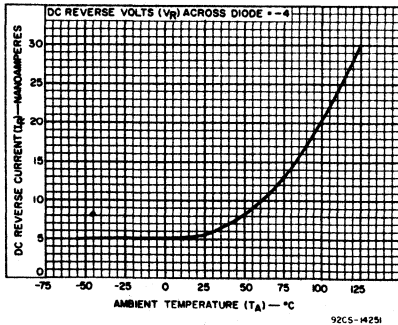


Fig. 3 — Reverse (leakage) current (any diode) as a function of temperature.

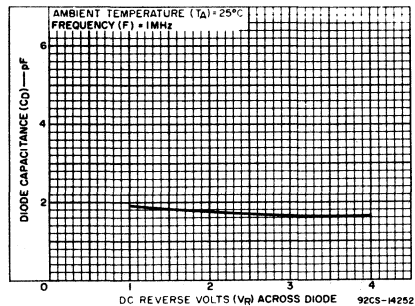


Fig. 4 — Diode capacitance (any diode) as a function of reverse voltage.

Absolute-Maximum Ratings:

DISSIPATION:	
Any one diode unit	20 max. mW
Total for device	120 max. mW
TEMPERATURE RANGE:	
Storage	-65 to +200 °C
Operating	-55 to +125 °C
DC Forward Current, I_F	25 mA
Peak Recurrent Forward Current, I_{FM}	100 mA
Peak Forward Surge Current, I_{FSM} (surge)	100 mA
VOLTAGE: See Table	

Absolute-Maximum Voltage Limits:

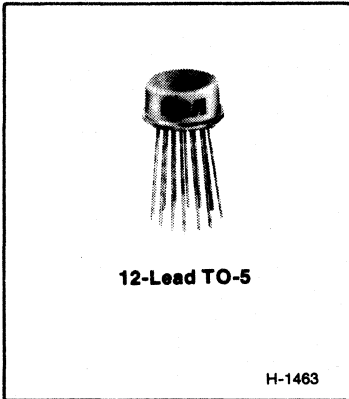
TERM.	VOLTAGE LIMITS		CONDITIONS	
	NEG.	POS.	TERM.	VOLT.
1	-3	+12	7	-6
2	-3	+12	7	-6
3	-3	+12	7	-6
4	-3	+12	7	-6
5	-3	+12	7	-6
6	-3	+12	7	-6
7	-18	0	1,2,3,6,8	0
8	-3	+12	7	-6
9	-3	+12	7	-6
10	NO CONNECTION			
CASE	INTERNALLY CONNECTED TO TERMINAL 7 DO NOT GROUND			

ELECTRICAL CHARACTERISTICS, at $T_A = 25^\circ\text{C}$

Characteristics Apply for Each Diode Unit, Unless Otherwise Specified

CHARACTERISTICS	SPECIAL TEST CONDITIONS	LIMITS			Units
		TYPE CA3019			
		Min.	Typ.	Max.	
DC Forward Voltage Drop	DC Forward Current (I_F) = 1 mA	-	0.73	0.78	V
DC Reverse Breakdown Voltage	DC Reverse Current (I_R) = -10 μA	4	6	-	V
DC Reverse Breakdown Voltage Between any Diode Unit and Substrate	DC Reverse Current (I_R) = -10 μA	25	80	-	V
DC Reverse (Leakage) Current	DC Reverse Voltage (V_R) = -4 V	-	0.0055	10	μA
DC Reverse (Leakage) Current Between any Diode Unit and Substrate	DC Reverse Voltage (V_R) = -4 V	-	0.010	10	μA
Magnitude of Diode Offset Voltage (Difference in DC Forward Voltage Drops of any Two Diode Units)	DC Forward Current (I_F) = 1 mA	-	1	5	mV
Single Diode Capacitance	Frequency (f) = 1 MHz DC Reverse Voltage (V_R) = -2V	-	1.8	-	pF
Diode Quad-to-Substrate Capacitance	Frequency (f) = 1 MHz DC Reverse Voltage (V_R) between Terminal 2,5,6, or 8 of Diode Quad and Terminal 7 (Substrate) = -2 V				
	Terminal 2 or 6 to Terminal 7	-	4.4	-	pF
	Terminal 5 or 8 to Terminal 7	-	2.7	-	pF
Series Gate Switching Pedestal Voltage		-	10	-	mV

CA3039



Diode Array

Six Matched Diodes on a Common Substrate

Ultra-Fast Low-Capacitance Matched Diodes

For Applications in Communications and Switching Systems

Features:

- Excellent reverse recovery time - 1 ns typ.
- Matched monolithic construction - V_F matched within 5 mV
- Low diode capacitance - $C_D = 0.65$ pF typical at $V_R = -2$ V

The RCA-CA3039 consists of six ultra-fast, low capacitance diodes on a common monolithic substrate. Integrated circuit construction assures excellent static and dynamic matching of the diodes, making the array extremely useful for a wide variety of applications in communication and switching systems.

Five of the diodes are independently accessible, the sixth shares a common terminal with the substrate.

For applications such as balanced modulators or ring modulators where capacitive balance is important, the substrate should be returned to a DC potential which is significantly more negative (with respect to the active diodes) than the peak signal applied.

Applications

- Balanced modulators or demodulators
- Ring modulators
- High speed diode gates
- Analog switches

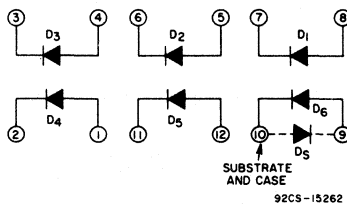


Fig. 1 — Schematic Diagram for CA3039.

ABSOLUTE MAXIMUM RATINGS at T_A = 25 °C

Dissipation:

Any one diode unit.	100	mW
Total for device	600	mW
For T _A > 55 °C	derate linearly 5.7 mW/°C	

Temperature Range:

Operating.	-55 to +125 °C
Storage	-65 to +150°C

Peak Inverse Voltage, PIV for: D ₁ -D ₅ . . .	5 V
D ₆	0.5 V

Peak Diode-to-Substrate Voltage, V_{DI}
for D₁-D₅ (term. 1,4,5,8 or 12 to term. 10) +20, -1 V

DC Forward Current, I_F 25 mA

Peak Recurrent Forward Current, I_F 100 mA

Peak Forward Surge Current, I_F (surge) . . . 100 mA

LEAD TEMPERATURE (During Soldering)

At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm)
from case for 10 seconds max. + 265 °C

ELECTRICAL CHARACTERISTICS, at T_A = 25° C

Characteristics apply for each diode unit, unless otherwise specified.

CHARACTERISTICS	SYMBOLS	SPECIAL TEST CONDITIONS	LIMITS			UNITS	CHARACTERISTIC CURVES FIG.
			MIN.	TYP.	MAX.		
DC Forward Voltage Drop	V _F	I _F = 50 μA	-	0.65	0.69	V	2
		1 mA	-	0.73	0.78	V	
		3 mA	-	0.76	0.80	V	
		10 mA	-	0.81	0.90	V	
DC Reverse Breakdown Voltage	V _{(BR)R}	I _R = -10 μA	5	7	-	V	-
DC Reverse Breakdown Voltage Between any Diode Unit and Substrate	V _{(BR)R}	I _R = -10 μA	20	-	-	V	-
DC Reverse (Leakage) Current	I _R	V _R = -4 V	-	0.016	100	nA	3
DC Reverse (Leakage) Current Between any Diode Unit and Substrate	I _R	V _R = -10 V	-	0.022	100	nA	4
Magnitude of Diode Offset Voltage (Difference in DC Forward Voltage Drops of any Two Diode Units)	V _{F1} - V _{F2}	I _F = 1 mA	-	0.5	5	mV	2
Temperature Coefficient of V _{F1} - V _{F2}	$\frac{\Delta V_{F1} - V_{F2} }{\Delta T}$	I _F = 1 mA	-	1	-	μV/°C	5
Temperature Coefficient of Forward Drop	$\frac{\Delta V_F}{\Delta T}$	I _F = 1 mA	-	-1.9	-	mV/°C	6
DC Forward Voltage Drop for Anode-to-Substrate Diode (D ₅)	V _F	I _F = 1 mA	-	0.65	-	V	-
Reverse Recovery Time	t _{rr}	I _F = 10 mA, I _R = 10 mA	-	1	-	ns	-
Diode Resistance	R _D	f = 1 kHz, I _F = 1 mA	25	30	45	Ω	7
Diode Capacitance	C _D	V _R = -2 V, I _F = 0	-	0.65	-	pF	8
Diode-to-Substrate Capacitance	C _{DI}	V _{DI} = +4 V, I _F = 0	-	3.2	-	pF	9

TYPICAL CHARACTERISTICS

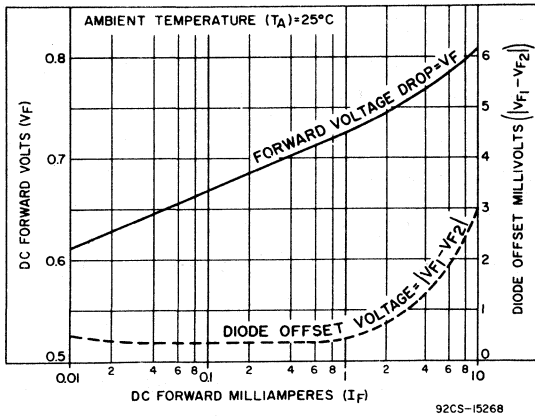


Fig. 2 - DC forward voltage drop (any diode) and diode offset voltage vs DC forward current

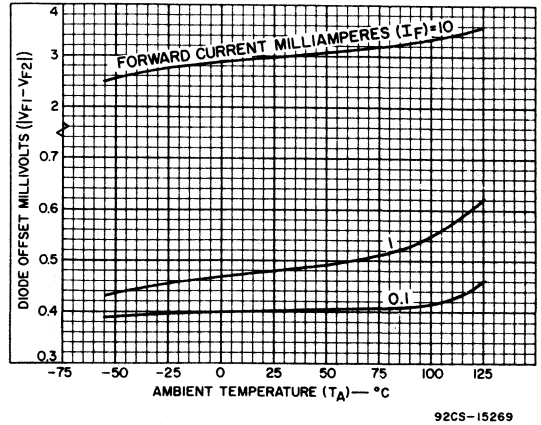


Fig. 5 - Diode offset voltage (any diode) vs temperature

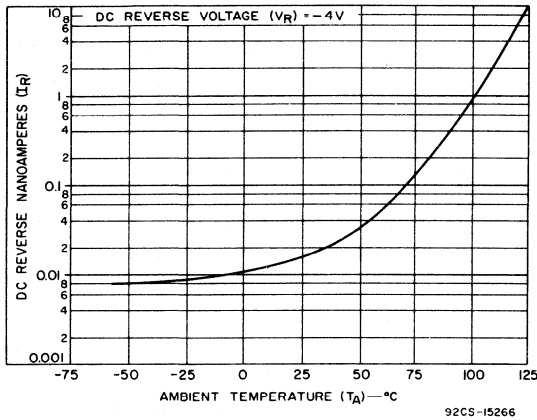


Fig. 3 - DC reverse (leakage) current (diodes 1,2,3,4,5) vs temperature

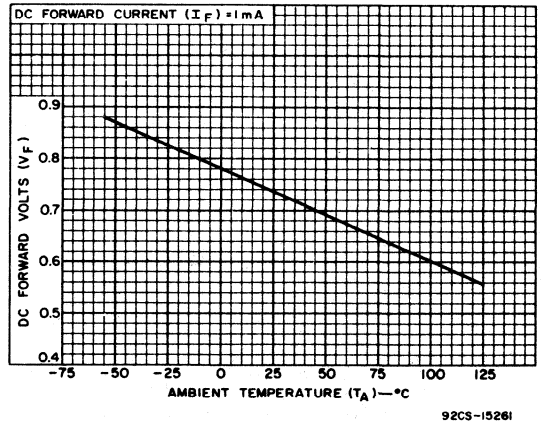


Fig. 6 - DC forward voltage drop (any diode) vs temperature

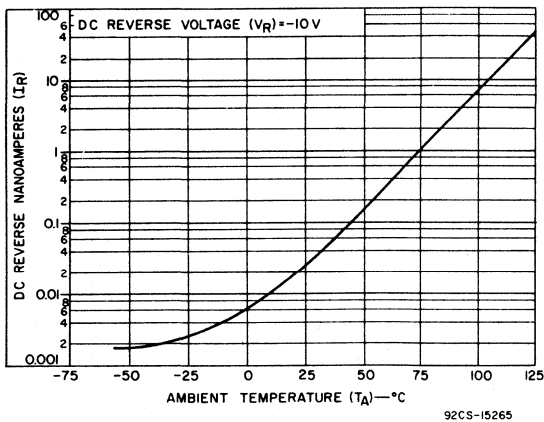


Fig. 4 - DC reverse (leakage) current between diodes (1,2,3,4,5) and substrate vs temperature

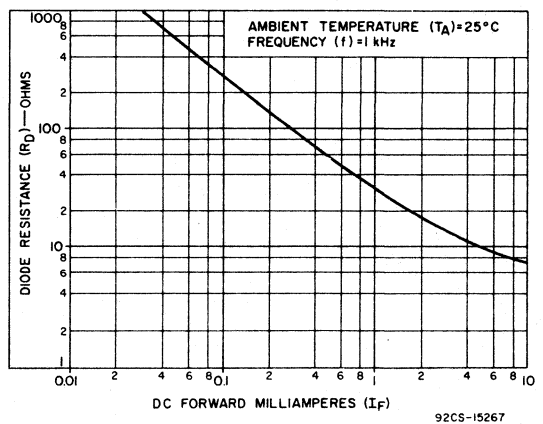


Fig. 7 - Diode resistance (any diode) vs DC forward current

TYPICAL CHARACTERISTICS

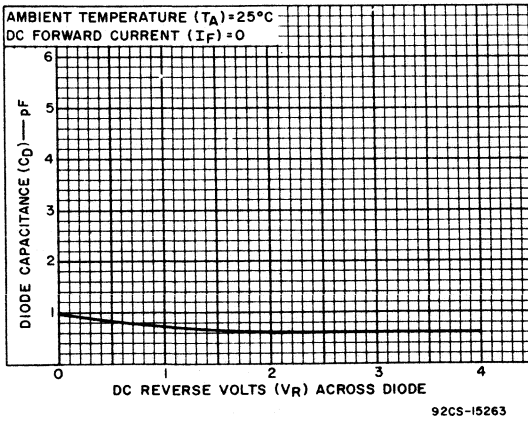


Fig. 8 - Diode capacitance (diodes 1,2,3,4,5) vs reverse voltage

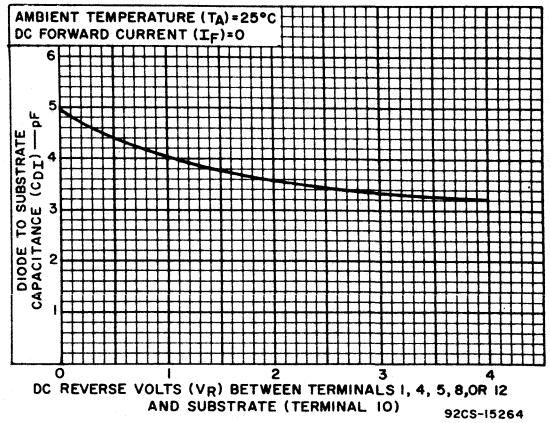
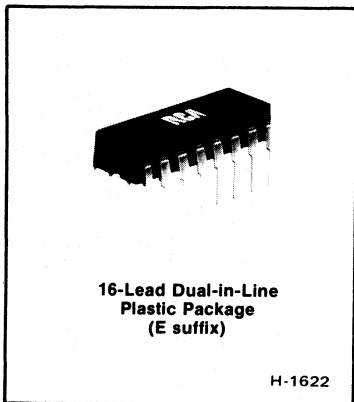


Fig. 9 - Diode-to-substrate capacitance vs reverse voltage

CA3141E



High-Voltage Diode Array

For Commercial, Industrial, and Military Applications

Features:

- Matched monolithic construction - V_F for each diode pair matched to within 0.55 mV (typ.) at $I_F = 1$ mA
- Low diode capacitance - 0.3 pF (typ.) at $V_R = 2$ V
- High diode-to-substrate breakdown voltage - 30 V (min.)
- Low reverse (leakage) current - 100 nA (max.)

Applications:

- Balanced modulators or demodulators
- Analog switches
- High-voltage diode gates
- Current ratio detectors

The RCA-CA3141E High-Voltage Diode Array consists of ten general-purpose high-reverse-breakdown diodes. Six diodes are internally connected to form three common-cathode diode pairs, and the remaining four diodes are internally connected to form two common-anode diode pairs. Integrated circuit construction assures excellent static and dynamic matching of the diodes, making the CA3141E extremely useful for a wide variety of applications in communications and switching systems.

The CA3141 is supplied in the 16-lead dual-in-line plastic package (E suffix), and in chip form (H suffix).

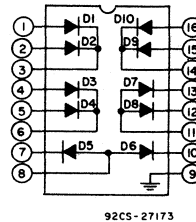


Fig. 1 — Terminal assignment.

MAXIMUM RATINGS, Absolute-Maximum Values:

PEAK INVERSE VOLTAGE (PIV)	30 V
PEAK DIODE-TO-SUBSTRATE VOLTAGE.....	30 V
PEAK FORWARD SURGE CURRENT [I_F (SURGE)]	100 mA
DC FORWARD CURRENT (I_F)	25 mA

DISSIPATION:

Any one diode unit	50 mW
Total Package:	
Up to 55°C.....	650 mW
For $T_A > 55^\circ\text{C}$	Derate linearly at 6.67 mW/°C

AMBIENT TEMPERATURE RANGE:

Operating	-55 to +125°C
Storage	-65 to +150°C

LEAD TEMPERATURE (During Soldering):

At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10s max.	+265°C
---	--------

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNIT	
		Min.	Typ.	Max.		
DC Forward Voltage Drop, V_F	I_F (Anode)	100 μA	—	0.7	0.9	V
		1 mA	—	0.78	1	
		10 mA	—	0.93	1.2	
DC Reverse Breakdown Voltage, $V_{(BR)R}$	$I_F = -10 \mu\text{A}$	30	50	—	V	
DC Breakdown Voltage Between Any Diode and Substrate, $V_{(BR)DI}$	$I_{DI} = 10 \mu\text{A}$	30	50	—	V	
DC Reverse (Leakage) Current, I_R	$V_F = -20 \text{ V}$	—	—	100	nA	
DC Reverse (Leakage) Current Between Any Diode and Substrate, I_{DI}	$V_{DI} = 20 \text{ V}$	—	—	100	nA	
Magnitude of Diode Offset Voltage Between Diode Pairs	$V_{DI} = 20 \text{ V}$ $I_{FA} = 1 \text{ mA}$	—	0.55	—	mV	
Temperature Coefficient of Forward Voltage Drop, $\Delta V_F / \Delta T$	$I_F = 1 \text{ mA}$	—	-1.5	—	mV/ $^\circ\text{C}$	
Reverse Recovery Time, t_{rr}	$I_F = 2 \text{ mA}$, $I_R = 2 \text{ mA}$	—	50	—	ns	
Diode Capacitance, C_D		See Fig. 5			pF	
Diode Anode-to-Substrate Capacitance, C_{DAI}		See Fig. 6			pF	
Diode Cathode-to-Substrate Capacitance, C_{DCI}		See Fig. 7			pF	
Magnitude of Cathode-to-Anode Current Ratio, $ I_{FC}/I_{FA} $	$I_{FA} = 1 \text{ mA}$, $V_{DS} = 10 \text{ V}$	0.9	0.96	—		

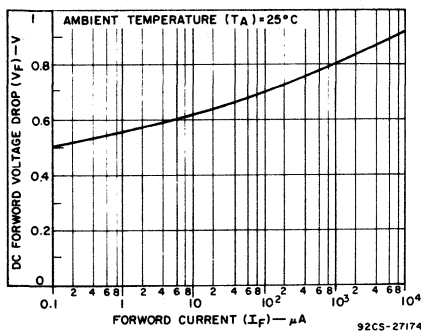


Fig. 2 — DC forward voltage drop vs. forward current.

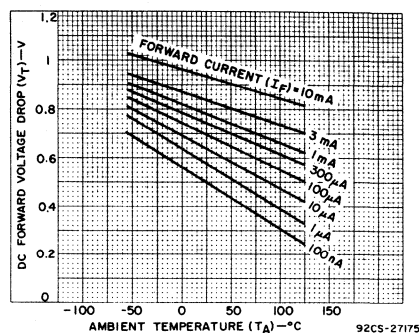


Fig. 3 — DC forward voltage drop vs. ambient temperature.

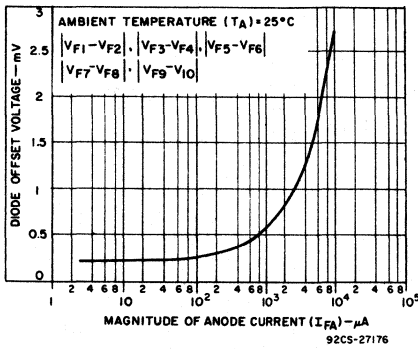


Fig. 4 - Diode offset voltage vs. magnitude of anode current.

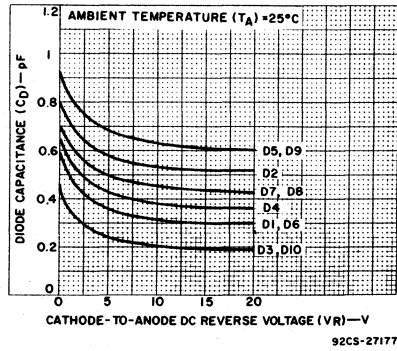


Fig. 5 - Diode capacitance vs. cathode-to-anode reverse voltage.

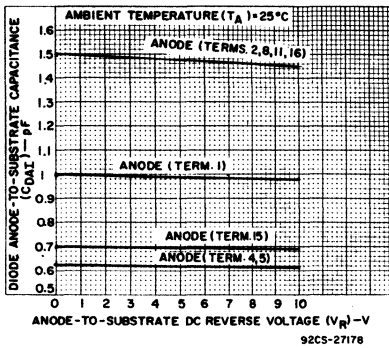


Fig. 6 - Diode anode-to-substrate capacitance vs. reverse voltage.

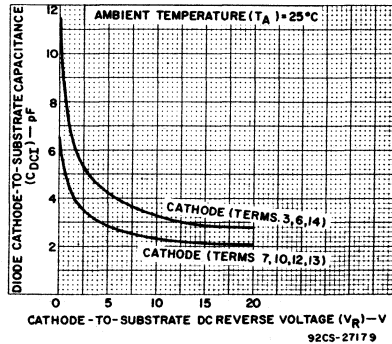


Fig. 7 - Diode cathode-to-substrate capacitance vs. cathode-to-substrate DC reverse voltage.

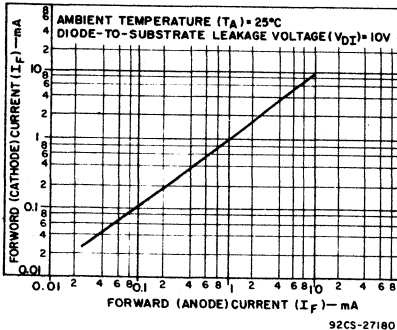


Fig. 8 - Forward (cathode) current vs. forward (anode) current.

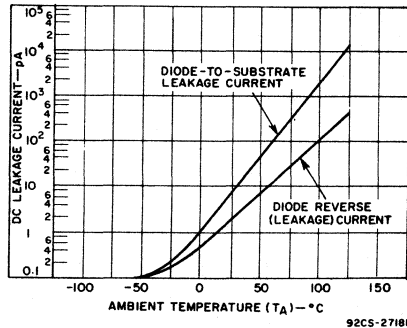
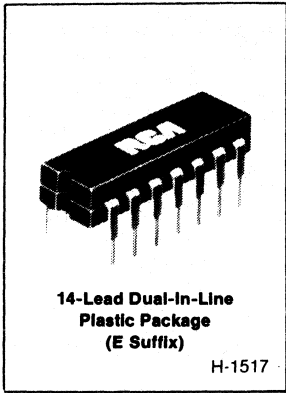


Fig. 9 - DC leakage current vs. ambient temperature.

CA1724, CA1725 Types



High-Current N-P-N Transistor Arrays

Four Individual Sealed-Junction High-Current N-P-N Transistors

Features:

- High Current — 1 A
- High Breakdown Voltage:
 - CA1725 = 80 V dc min. $V_{(BR)CES}$
@ $I_C = 10 \mu A$
 - CA1724 = 70 V dc min. $V_{(VR)CES}$
@ $I_C = 10 \mu A$

The RCA-CA1724 and -CA1725 are high-current n-p-n transistor arrays each containing 4 individual sealed-junction high-current n-p-n transistors. They are intended for high-current driver applications.

These devices are alike except for breakdown voltage ratings.

The CA1724 and CA1725 are supplied in a 14-lead dual-in-line plastic package and operate over the full military temperature range of $-55^\circ C$ to $+125^\circ C$.

- Silicon Nitride Passivated
- Platinum Silicide Ohmic Contacts
- Electrically similar and pin compatible with industry types MPQ3724, MPQ3725; FPQ3724, FPQ3725; DH3724, DH3725; SP3724, SP3725 in similar packages

Applications

- High-Current LED Driver
- High-Voltage Switching
- Relay and Solenoid Driver
- Lamp Driver

Comparison of High Current N-P-N Arrays

CHARACTERISTIC	CA1725			CA3725			CA3138A		
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.
$V_{CEO(sus)}$	50	58	—	50	—	—	15	20	—
$V_{(BR)CBO}$	80	94	—	80	—	—	25	60	—
$V_{(BR)EBO}$	6	6.9	—	6	—	—	5	7.2	—
$h_{FE} @ 1A$	20	25	—	20	—	—	40	170	—
$h_{FE} @ 500 mA$	30	35	—	30	—	—	95	170	—
$h_{FE} @ 100 mA$	35	40	—	35	—	—	80	160	450
$V_{CE(SAT)} @ 500 mA$	—	0.38	0.5	—	—	0.5	—	0.26	0.4
$t_{ON} @ 500 mA$	—	38	—	—	—	40	—	31	—
$t_{OFF} @ 500 mA$	—	185	—	—	—	60	—	105	—
CEB	—	100	—	—	95	—	—	77	—
CGB	—	12.5	—	—	12	—	—	18	—

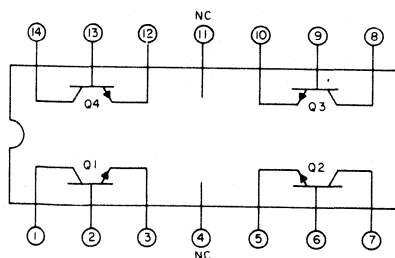
Linear Integrated Circuits

CA1724, CA1725 Types

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

Characteristic	Test Conditions	LIMITS						Units
		CA1724			CA1725			
		Min.	Typ.	Max.	Min.	Typ.	Max.	
Collector-to-Emitter Sustaining Voltage, $V_{CEO(sus)}$ *	$I_C = 10\text{ mA}, I_B = 0$	40	45	—	50	58	—	V
Collector-to-Emitter Breakdown Voltage, $V_{(BR)CES}$	$I_C = 10\ \mu\text{A}, I_B = 0$	70	75	—	80	94	—	V
Collector-to-Base Breakdown Voltage, $V_{(BR)CBO}$	$I_C = 10\ \mu\text{A}, I_E = 0$	70	75	—	80	94	—	V
Emitter-to-Base Breakdown Voltage, $V_{(BR)EBO}$	$I_E = 10\ \mu\text{A}, I_C = 0$	6	6.9	—	6	6.9	—	V
Base-to-Emitter Saturation Voltage, $V_{BE(sat)}$ *	$I_C = 500\text{ mA}, I_B = 50\text{ mA}$	0.75	0.89	1.0	0.75	0.9	1.0	V
Collector-to-Emitter Saturation Voltage, $V_{CE(sat)}$	$I_C = 500\text{ mA}, I_B = 50\text{ mA}$	—	0.36	0.5	—	0.38	0.5	V
Collector-Cutoff Current, I_{CBO}	$V_{CB} = 40\text{ V}, I_E = 0$	—	0.3	1.7	—	0.3	1.7	μA
Static Forward Current Transfer Ratio (Beta), h_{FE}	$I_C = 100\text{ mA}, V_{CE} = 1.0\text{ V}$	35	40	—	35	40	—	
	$I_C = 500\text{ mA}, V_{CE} = 1.0\text{ V}$	30	35	—	30	35	—	
	$I_C = A, V_{CE} = 1.0\text{ V}$	20	25	—	20	25	—	
	$I_C = A, V_{CE} = 1.0\text{ V}$							
Turn-On Time (See Test Ckt.Fig.6), t_{on}	$I_C = 500\text{ mA}, I_{B1} = 50\text{ mA}$	—	38	—	—	38	—	ns
Turn-Off Time (See Test Ckt.Fig.6), t_{off}	$I_C = 500\text{ mA}, I_{B1} = I_{B2} = 50\text{ mA}$	—	185	—	—	185	—	ns
Emitter-to-Base Capacitance, C_{eb}	$I_C = 0, V_{EB} = 0.5\text{ V}$	—	102	—	—	100	—	pF
Collector-to-Base Capacitance, C_{cb}	$I_E = 0, V_{CB} = 10\text{ V}$	—	14	—	—	12.5	—	pF

* Pulse Conditions: width = 300 μs ; duty cycle = 1%.



92CS - 24299

Fig. 1—Terminal diagram (top view).

CA1724, CA1725 Types

MAXIMUM RATINGS, Absolute-Maximum Values:

	CA1724	CA1725	
COLLECTOR-TO-EMITTER VOLTAGE V_{CE0}	40	50	V
With Base Open			
COLLECTOR-TO-BASE VOLTAGE V_{CB0}	70	80	V
EMITTER-TO-BASE VOLTAGE V_{EB0}	6		V
With Collector Open			
COLLECTOR CURRENT I_C	1.0		A
POWER DISSIPATION: P_D			
For Each Transistor	1.0		W
Total Package	2.0		W
At T_A above 25°C derate linearly (Total Package)	20		mw/°C
AMBIENT TEMPERATURE RANGE:			
Operating	-55 to +125		°C
Storage	-65 to +150		°C
LEAD TEMPERATURE (DURING SOLDERING):			
At distance 1/32" (3.17 mm) from seating plane for 10 s max.	300		°C

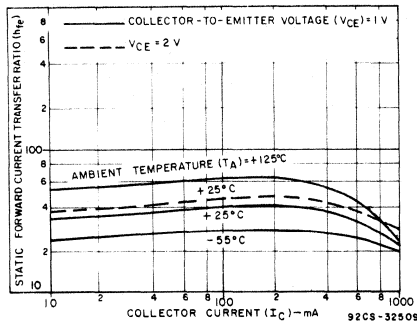


Fig. 2—Static forward current transfer ratio as a function of collector current.

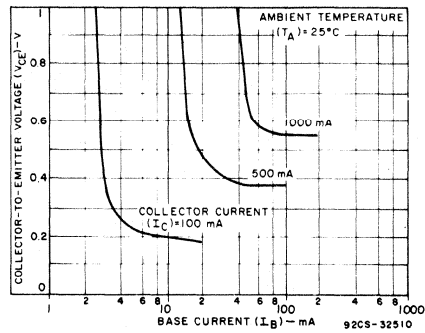


Fig. 3—Collector-to-emitter voltage as a function of base current.

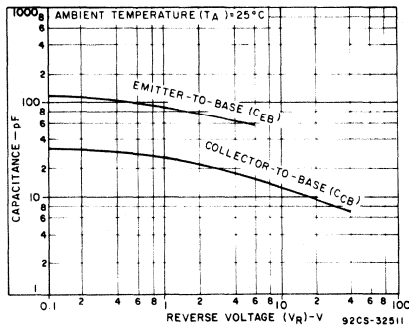


Fig. 4—Capacitance as a function of reverse voltage.

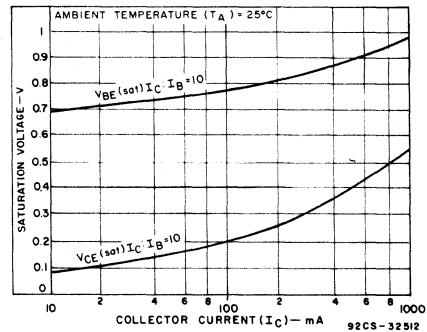


Fig. 5—Saturation voltage as a function of collector current.

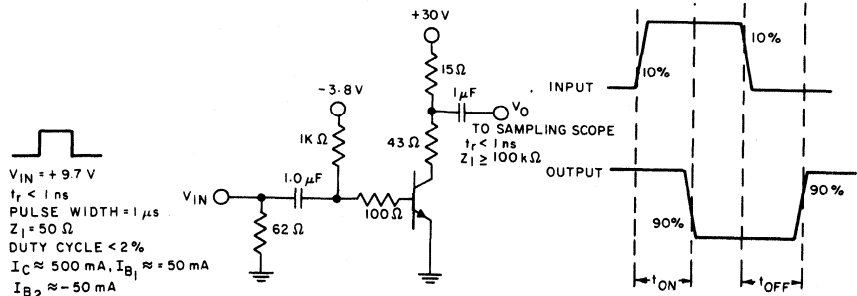
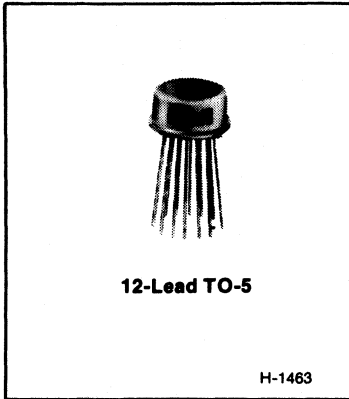


Fig. 6 — Switching time test circuit.

92CM-24300

CA3018, CA3018A



General-Purpose Transistor Arrays

Two Isolated Transistors and
a Darlington-Connected Transistor Pair
For Low-Power Applications at Frequencies
from DC Through the VHF Range

Features:

- Matched monolithic general purpose transistors
- H_{FE} matched $\pm 10\%$
- V_{BE} matched ± 2 mV CA3018A (± 5 mV CA3018)
- Operation from DC to 120 MHz
- Wide operating current range
- CA3018A performance characteristics controlled from 10 μ A to 10 mA
- Low noise figure - 3.2 dB typical at 1 KHz
- Full military temperature range capability (-55 to +125° C)

Applications

- General use in signal processing systems in DC through VHF range
- Custom designed differential amplifiers
- Temperature compensated amplifiers
- See RCA Application Note, ICAN-5296 "Application of the RCA CA3018 Integrated-Circuit Transistor Array" for suggested applications.

The CA3018 and CA3018A consist of four general purpose silicon n-p-n transistors on a common monolithic substrate.

Two of the four transistors are connected in the Darlington configuration. The substrate is connected to a separate terminal for maximum flexibility.

The transistors of the CA3018 and the CA3018A are well suited to a wide variety of applications in low-power sys-

tems in the DC through VHF range. They may be used as discrete transistors in conventional circuits but in addition they provide the advantages of close electrical and thermal matching inherent in integrated circuit construction.

The CA3018A is similar to the CA3018 but features tighter control of current gain, leakage, and offset parameters making it suitable for more critical applications requiring premium performance.

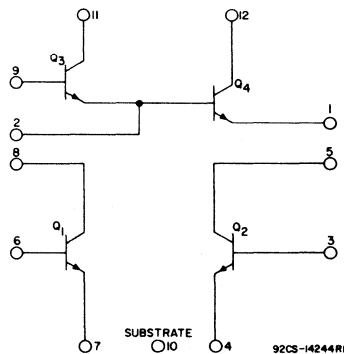


Fig. 1 — Schematic Diagram for CA3018 and CA3018A

CA3018, CA3018A

Maximum Ratings, Absolute-Maximum Values, at TA=25°C

The following ratings apply for each transistor in the device:

	CA3018	CA3018A	
Power Dissipation, P:			
Any one transistor	300	300	mW
Total package	450	450	mW

Derate at 5 mW/°C for TA > 85°C

Temperature Range:

Operating	-55 to + 125	-55 to + 125°C
Storage	-65 to + 150	-65 to + 150°C

	CA3018	CA3018A	
Collector-to-Emitter Voltage, V _{CEO}	15	15	V
Collector-to-Base Voltage, V _{CB0}	20	30	V
Collector-to-Substrate Voltage, V _{CIO} *	20	40	V
Emitter-to-Base Voltage, V _{EBO}	5	5	V
Collector Current, I _C	50	50	mA

*The collector of each transistor of the CA3018 and CA3018A is isolated from the substrate by an integral diode. The substrate (terminal 10) must be connected to the most negative point in the external circuit to maintain isolation between transistors and to provide for normal transistor action.

LEAD TEMPERATURE (During Soldering)
 At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm)
 from case for 10 seconds max. +265°C

Characteristics apply for each transistor in the CA3018 and CA3018A as specified.

ELECTRICAL CHARACTERISTICS at TA = 25°C	SYMBOLS	SPECIAL TEST CONDITIONS	CA3018 LIMITS			CA3018A LIMITS			Units	CHARACTERISTICS CURVES
			Min.	Typ.	Max.	Min.	Typ.	Max.		
STATIC CHARACTERISTICS										
Collector-Cutoff Current	I _{CB0}	V _{CB} =10V, I _E =0	-	0.002	100	-	0.002	40	nA	2
Collector-Cutoff Current	I _{CEO}	V _{CE} =10V, I _B =0	-	See Curve	5	-	See Curve	0.5	μA	3
Collector-Cutoff Current Darlington Pair	I _{CE0D}	V _{CE} =10V, I _B =0	-	-	-	-	-	5	μA	-
Collector-to-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C =1mA, I _B =0	15	24	-	15	24	-	V	-
Collector-to-Base Breakdown Voltage	V _{(BR)CBO}	I _C =10μA, I _E =0	20	60	-	30	60	-	V	-
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =10μA, I _C =0	5	7	-	5	7	-	V	-
Collector-to-Substrate Breakdown Voltage	V _{(BR)CIO}	I _C =10μA, I _{C1} =0	20	60	-	40	60	-	V	-
Collector-to-Emitter Saturation Voltage	V _{CES}	I _B =1mA, I _C =10mA	-	0.23	-	-	0.23	0.5	V	-
Static Forward Current Transfer Ratio	h _{FE}	V _{CE} =3V, { I _C =10mA I _C =1mA I _C =100μA	-	100 100 54	-	50 60 30	100 100 54	-	-	4
Magnitude of Static-Beta Ratio (Isolated Transistors Q ₁ and Q ₂)		V _{CE} =3V, I _{C1} =I _{C2} =1mA	0.9	0.97	-	0.9	0.97	-	-	4
Static Forward Current Transfer Ratio Darlington Pair (Q ₃ & Q ₄)	h _{FED}	V _{CE} =3V { I _C =1mA I _C =100μA	1500	5400	-	2000	5400	-	-	5
Base-to-Emitter Voltage	V _{BE}	V _{CE} =3V, { I _E =1mA I _E =10mA	-	0.715 0.800	-	0.600	0.715 0.800	0.800 0.900	V	6
Input Offset Voltage	V _{BE1} - V _{BE2}	V _{CE} =3V, I _E =1mA	-	0.48	5	-	0.48	2	mV	6,8
Temperature Coefficient: Base-to-Emitter Voltage Q ₁ , Q ₂	ΔV _{BE} /ΔT	V _{CE} =3V, I _E =1mA	-	-1.9	-	-	-1.9	-	mV/°C	7
Base (Q ₃)-to-Emitter (Q ₄) Voltage-Darlington Pair	V _{BED} (V ₉₋₁)	V _{CE} =3V, { I _E =10mA I _E =1mA	-	1.46 1.32	-	-	1.46 1.32	1.60 1.50	V	9
Temperature Coefficient: Base-to-Emitter Voltage Darlington Pair-Q ₃ , Q ₄	ΔV _{BED} /ΔT	V _{CE} =3V, I _E =1mA	-	4.4	-	-	4.4	-	mV/°C	10
Temperature Coefficient: Magnitude of Input-Offset Voltage	V _{BE1} - V _{BE2} /ΔT	V _{CC} =+6V, V _{EE} =-6V, I _{C1} =I _{C2} =1mA	-	10	-	-	10	-	μV/°C	-

Linear Integrated Circuits

CA3018, CA3018A

ELECTRICAL CHARACTERISTICS, (CONT'D)

DYNAMIC CHARACTERISTICS										
Low Frequency Noise Figure	NF	$f=1\text{ KHz}, V_{CE}=3V, I_C=100\mu A$ Source resistance=1 K Ω	-	3.25	-	-	3.25	-	dB	11(b)
Low-Frequency, Small-Signal Equivalent-Circuit Characteristics:										
Forward Current-Transfer Ratio	h_{fe}	$f=1\text{ kHz}, V_{CE}=3V, I_C=1\text{ mA}$	-	110	-	-	110	-	-	12
Short-Circuit Input Impedance	h_{ie}		-	3.5	-	-	3.5	-	K Ω	12
Open-Circuit Output Impedance	h_{oe}		-	15.6	-	-	15.6	-	μmho	12
Open-Circuit Reverse Voltage-Transfer Ratio	h_{re}		-	1.8×10^{-4}	-	-	1.8×10^{-4}	-	-	12
Admittance Characteristics:										
Forward Transfer Admittance	Y_{fe}	$f=1\text{ MHz}, V_{CE}=3V, I_C=1\text{ mA}$	-	$31-j1.5$	-	-	$31-j1.5$	-	mmho	13
Input Admittance	Y_{ie}		-	$0.3+j0.04$	-	-	$0.3+j0.04$	-	mmho	14
Output Admittance	Y_{oe}		-	$0.001+j0.03$	-	-	$0.001+j0.03$	-	mmho	15
Reverse Transfer Admittance	Y_{re}		See Curve		See Curve		mmho		16	
Gain-Bandwidth Product	f_T	$V_{CE}=3V, I_C=3\text{ mA}$	300	500	-	300	500	-	MHz	17
Emitter-to-Base Capacitance	C_{EB}	$V_{EB}=3V, I_E=0$	-	0.6	-	-	0.6	-	pF	-
Collector-to-Base Capacitance	C_{CB}	$V_{CB}=3V, I_C=0$	-	0.58	-	-	0.58	-	pF	-
Collector-to-Substrate Capacitance	C_{CI}	$V_{CI}=3V, I_C=0$	-	2.8	-	-	2.8	-	pF	-

STATIC CHARACTERISTICS

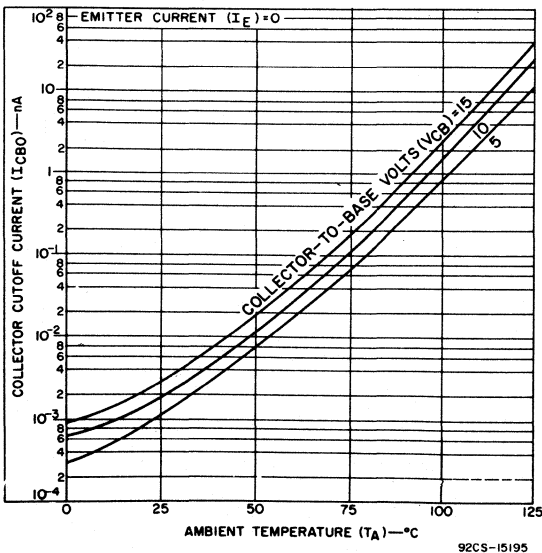


Fig.2 - Typical Collector-To-Base Cutoff Current vs Ambient Temperature for Each Transistor.

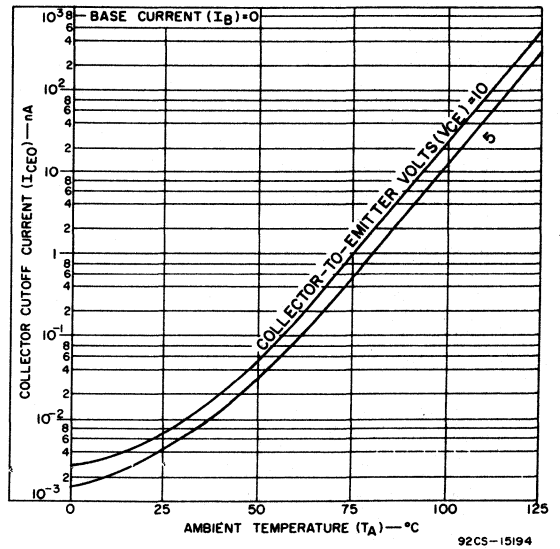


Fig.3 - Typical Collector-To-Emitter Cutoff Current vs Ambient Temperature for Each Transistor.

CA3018, CA3018A

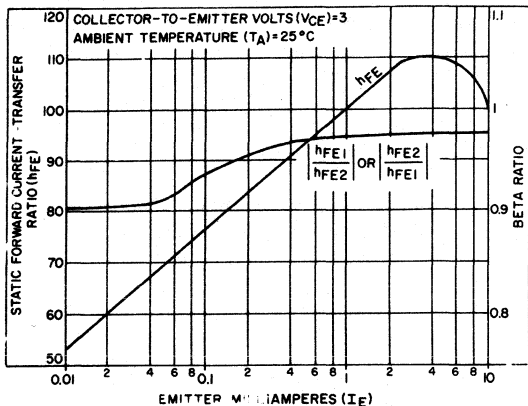


Fig.4 - Typical Static Forward Current-Transfer Ratio and Beta Ratio for Transistors Q₁ and Q₂ vs Emitter Current.

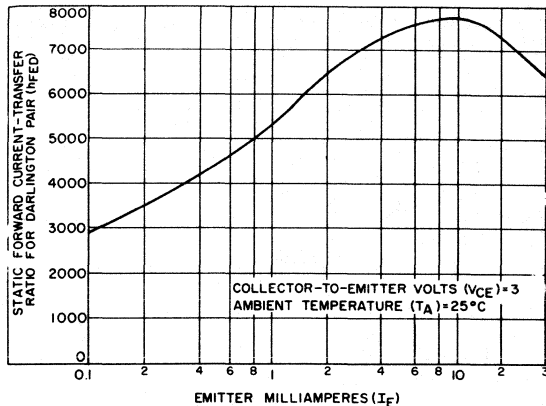


Fig.5 - Typical Static Forward Current - Transfer Ratio for Darlington-connected Transistors Q₃ and Q₄ vs Emitter Current.

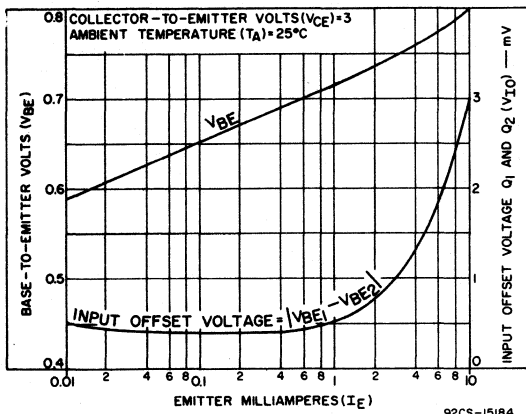


Fig.6 - Typical Static Base-to-Emitter Voltage Characteristic and Input Offset Voltage for Q₁ and Q₂ vs Emitter Current.

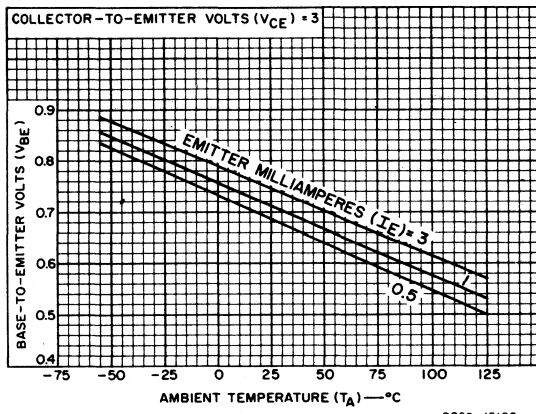


Fig.7 - Typical Base-To-Emitter Voltage Characteristic for Each Transistor vs Ambient Temperature

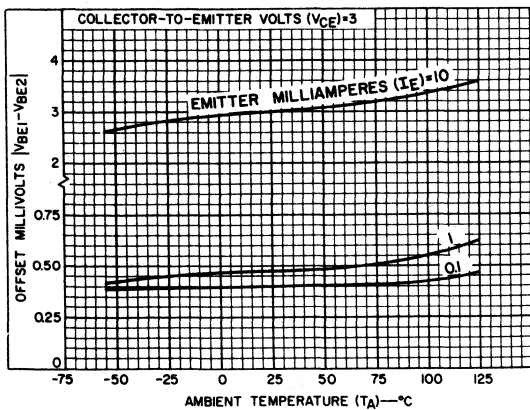


Fig.8 - Typical Offset Voltage Characteristic vs Ambient Temperature

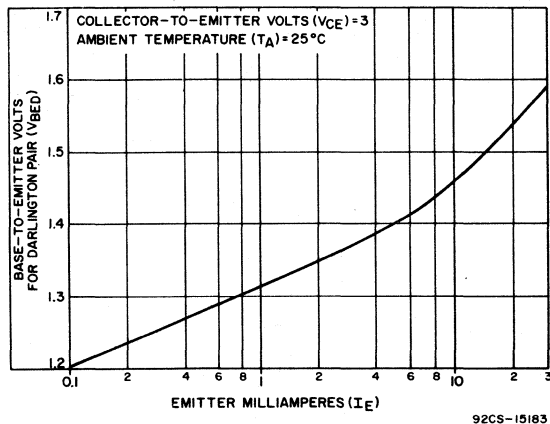


Fig.9 - Typical Static Input Voltage Characteristic for Darlington Pair (Q₃ and Q₄) vs Emitter Current

Linear Integrated Circuits

CA3018, CA3018A

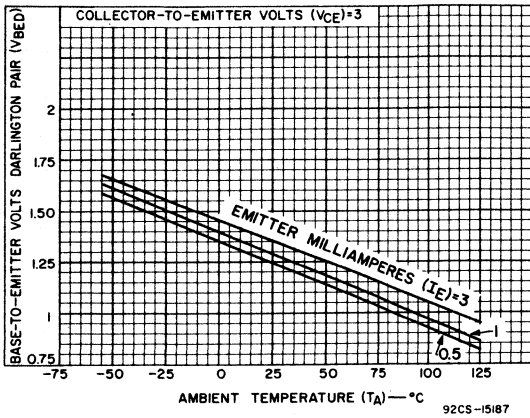


Fig. 10 - Typical Static Input Voltage Characteristic for Darlingon Pair (Q_3 and Q_4) vs Ambient Temperature.

TYPICAL DYNAMIC CHARACTERISTICS FOR EACH TRANSISTOR

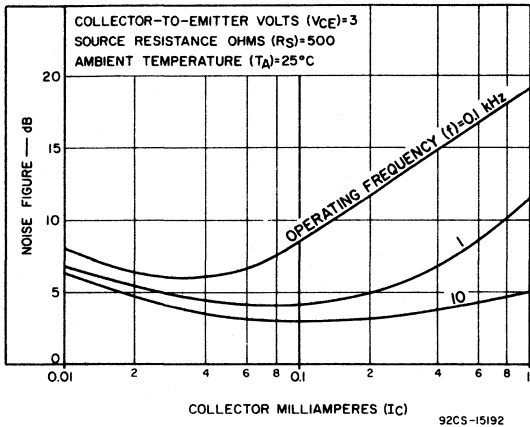


Fig. 11(a) - Noise Figure vs Collector Current, $R_S = 500 \Omega$.

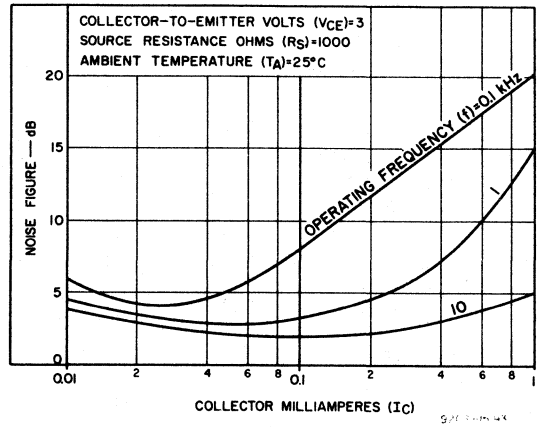


Fig. 11(b) - Noise Figure vs Collector Current, $R_S = 1 K \Omega$.

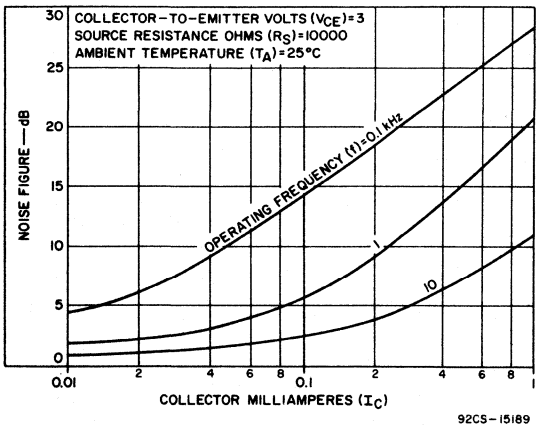


Fig. 11(c) - Noise Figure vs Collector Current, $R_S = 10 K \Omega$.

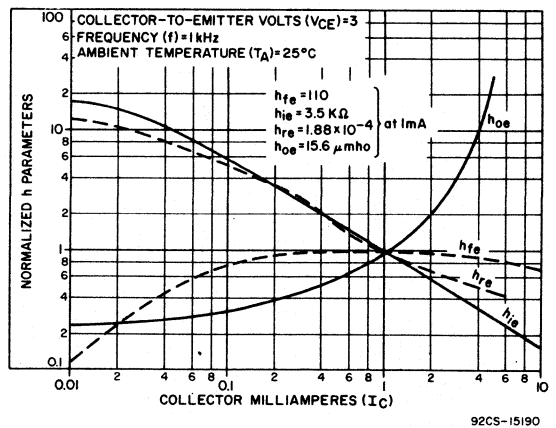


Fig. 12 - Forward Current-Transfer Ratio (h_{fe}), Short-Circuit Input Impedance (h_{ie}), Open-Circuit Output Impedance (h_{oe}), and Open-Circuit Reverse Voltage-Transfer Ratio (h_{re}) vs Collector Current

CA3018, CA3018A

TYPICAL DYNAMIC CHARACTERISTICS FOR EACH TRANSISTOR

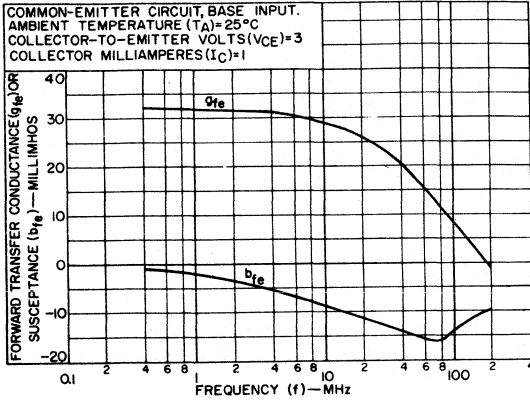


Fig. 13 - Forward Transfer Admittance (Y_{fe})

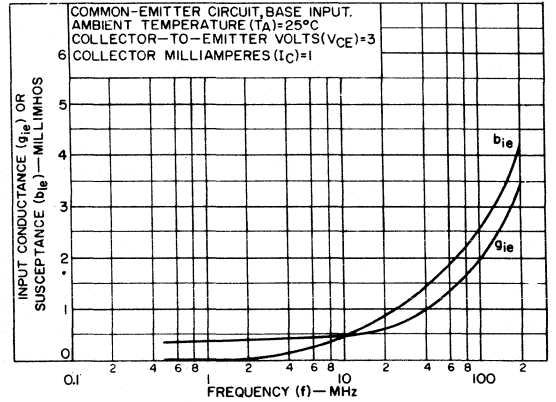


Fig. 14 - Input Admittance (Y_{ie})

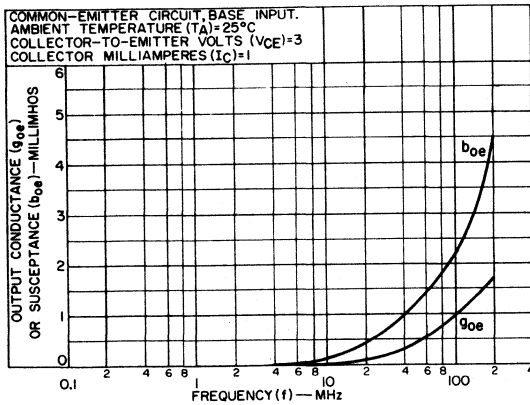


Fig. 15 - Output Admittance (Y_{oe})

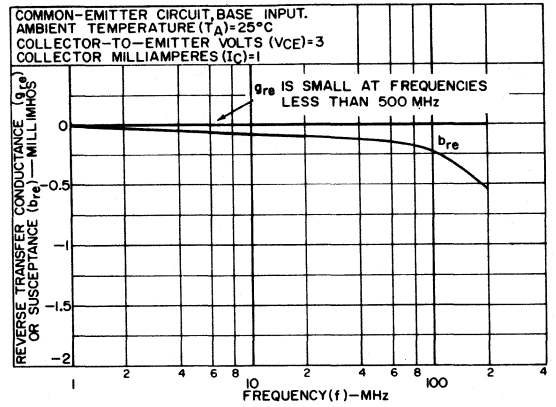


Fig. 16 - Reverse Transfer Admittance (Y_{re})

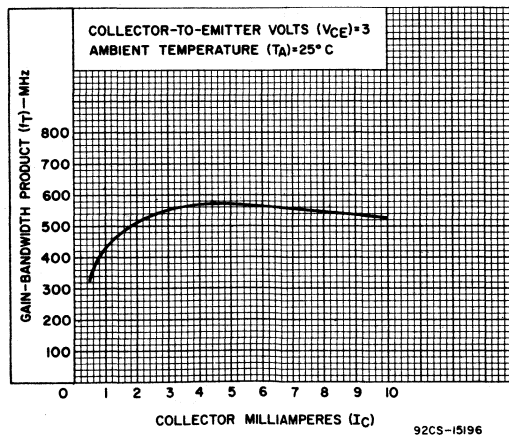
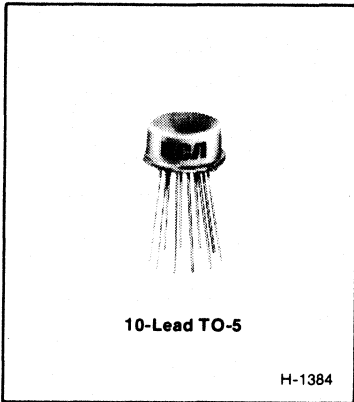


Fig. 17 - Typical Gain-Bandwidth Product (f_T) vs Collector Current

CA3036



Dual Darlington Array

Features

- Two independent low-noise wide-band amplifier channels
- Particularly useful for preamplifier and low-level amplifier applications in single-channel and stereo systems
- Wide application in low-noise industrial instrumentation amplifiers

Applications

- Stereo phonograph preamplifiers
- Low-level stereo and single-channel amplifier stages
- Low-noise, emitter-follower differential amplifiers
- Operational amplifier drivers

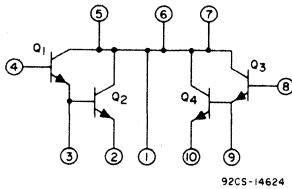


Fig. 1 - Schematic diagram for CA3036.

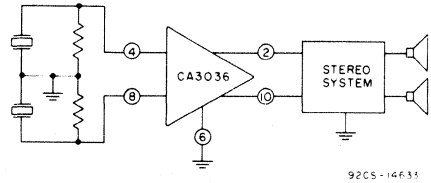


Fig. 2 - Block diagram of stereo system using CA3036 as phono preamplifier.

MAXIMUM RATINGS, Absolute-Maximum Values:

POWER DISSIPATION, P:	
ANY ONE TRANSISTOR	300 max. mW
TOTAL FOR ARRAY	300 max. mW
TEMPERATURE RANGE:	
OPERATING	-55 to +125°C
STORAGE	-65 to +200°C

THE FOLLOWING RATINGS APPLY FOR EACH TRANSISTOR IN THE ARRAY:

COLLECTOR-TO-EMITTER VOLTAGE, V_{CE0}	15 max. V
COLLECTOR-TO-BASE VOLTAGE, V_{CB0}	30 max. V
EMITTER-TO-BASE VOLTAGE, V_{EB0}	5 max. V
COLLECTOR CURRENT, I_C	50 max. mA

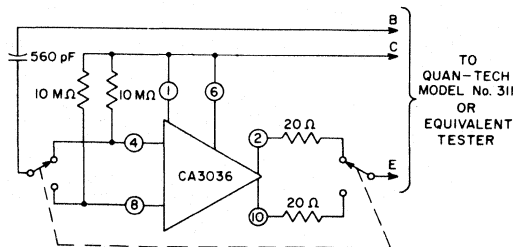


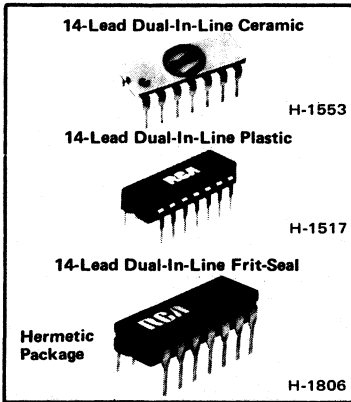
Fig.3 - Noise Voltage Test Circuit for CA3036.

ELECTRICAL CHARACTERISTICS, at $T_A = 25^\circ\text{C}$

CHARACTERISTICS		SYMBOLS	TEST CONDITIONS	LIMITS			UNITS
				TYPE CA3036			
				Min.	Typ.	Max.	
For Each Transistor (Q1, Q2, Q3, Q4)	Collector-Cutoff Current	I_{CBO}	$V_{CB} = 5\text{V}, I_E = 0$	--	--	0.5	μA
	Collector-Cutoff Current	I_{CEO}	$V_{CE} = 10\text{V}, I_B = 0$	--	--	5	μA
	Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 1\text{mA}, I_B = 0$	15	20	--	V
	Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 10\mu\text{A}, I_E = 0$	30	44	--	V
	Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 10\mu\text{A}, I_C = 0$	5	6	--	V
For Either Input Transistor (Q1 or Q3)	Static Forward Current-Transfer Ratio	h_{FE}	I_{C1} or $I_{C3} = 1\text{mA}$	30	82	--	--
For Either Darlington Pair (Q1, Q2 or Q3, Q4)	Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO(D)}$	I_{E2} or $I_{E4} = 10\mu\text{A}$	10	12.6	--	V
	Static Forward Current-Transfer Ratio	$h_{FE(D)}$	$I_{C1} + I_{C2}$ or $I_{C3} + I_{C4}$ } = 1 mA	1000	4540	--	--
For Each Input Transistor (Q1 or Q3)	Short-Circuit Forward Current-Transfer Ratio	h_{fe}	$f = 1\text{kHz}$ I_{C1} or $I_{C3} = 1\text{mA}$	--	82	--	--
	Short-Circuit Input Impedance	h_{ie}		--	2.6K	--	Ω
	Open-Circuit Output Admittance	h_{oe}		--	7	--	μmho
	Open-Circuit Reverse Voltage-Transfer Ratio	h_{re}		--	9.8×10^{-5}	--	--
For Either Darlington Pair (Q1, Q2 or Q3, Q4)	Short-Circuit Forward Current-Transfer Ratio	$h_{fe(D)}$	$f = 1\text{kHz}$ $I_{C1} + I_{C2}$ or $I_{C3} + I_{C4}$ } = 1 mA	--	1300	--	--
	Short-Circuit Input Impedance	$h_{ie(D)}$		--	82K	--	Ω
	Open-Circuit Output Admittance	$h_{oe(D)}$		--	108	--	μmho
	Open-Circuit Reverse Voltage-Transfer Ratio	$h_{re(D)}$		--	2.7×10^{-3}	--	--
	Voltage Gain	$A_v(D)$		--	26	--	dB
	Power Gain	$G_p(D)$		--	47	--	dB
	Noise Voltage See Fig.3 for Test Circuit	E_N		$f = 100\text{Hz}$	--	0.2	3
		$f = 1\text{kHz}$	--	0.05	0.3		
		$f = 10\text{kHz}$	--	0.012	0.1		
For Either Input Transistor (Q1 or Q3)	Forward Transfer Admittance	y_{fe}	$f = 50\text{MHz}$ I_{C1} or $I_{C3} = 2\text{mA}$	--	$0.68 + j 7.9$	--	mmho
	Input Admittance (Output Short-Circuited)	y_{ie}		--	$4.14 + j 5.95$	--	mmho
	Output Admittance (Input Short-Circuited)	y_{oe}		--	$1.94 + j 2.64$	--	mmho
	Reverse Transfer Admittance (Input Short-Circuited)	y_{re}		--	Negligible	--	mmho
For either Darlington Pair (Q1, Q2 or Q3, Q4)	Input Admittance (Output Short-Circuited)	$y_{ie(D)}$	$f = 50\text{MHz}$ $I_{C1} + I_{C2}$ or $I_{C3} + I_{C4}$ } = 2 mA	--	$1.71 + j 2.8$	--	mmho
	Output Admittance (Input Short-Circuited)	$y_{oe(D)}$		--	$3.96 + j 2.6$	--	mmho
	Gain-Bandwidth Product	$f_T(D)$		150	200	--	MHz

Linear Integrated Circuits

CA3045, CA3046 Types



General-Purpose Transistor Arrays

THREE ISOLATED TRANSISTORS AND ONE DIFFERENTIALLY-CONNECTED TRANSISTOR PAIR

For Low-Power Applications at Frequencies
from DC through the VHF Range

Features

- Two matched pairs of transistors
V_{BE} matched ± 5 mV
Input offset current 2 μA max. at I_C = 1 mA
- 5 general purpose monolithic transistors

The CA3045 and CA3046 each consist of five general-purpose silicon n-p-n transistors on a common monolithic substrate. Two of the transistors are internally connected to form a differentially-connected pair.

The transistors of the CA3045 and CA3046 are well suited to a wide variety of applications in low power systems in the DC through VHF range. They may be used as discrete transistors in conventional circuits. However, in addition, they provide the very significant inherent integrated circuit advantages of close electrical and thermal matching.

The CA3045 is supplied in a 14-lead dual-in-line hermetic (welded-seal) ceramic package and the CA3045F in a 14-lead dual-in-line hermetic (frit-seal) ceramic package.

The CA3046 is electrically identical to the CA3045 but is supplied in a dual-in-line plastic package for applications requiring only a limited temperature range.

- Operation from DC to 120 MHz
- Wide operating current range
- Low noise figure - - 3.2 dB typ. at 1 kHz
- Full military temperature range for CA3045
-55 to +125°C

Applications

- General use in all types of signal processing systems operating anywhere in the frequency range from DC to VHF
- Custom designed differential amplifiers
- Temperature compensated amplifiers
- See RCA Application Note, ICAN-5296 "Application of the RCA-CA3018 Integrated-Circuit Transistor Array" for suggested applications.

The CA3045 and CA3046 are available in the packages shown below

Package	Suffix Letter	CA3045	CA3046
14-Lead Dual-In-Line Plastic	E		✓
14-Lead Dual-In-Line Ceramic	D	✓	
14-Line Dual-In-Line Frit-Seal Ceramic	F	✓	
Beam Lead	L	✓	
Chip	H	✓	

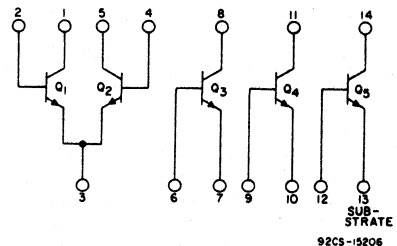


Fig.1 - Schematic diagram.

CA3045, CA3046 Types

ABSOLUTE MAXIMUM RATINGS AT T_A = 25°C

	CA3045		CA3046, CA3045F		
	Each Transistor	Total Package	Each Transistor	Total Package	
Power Dissipation:					
T _A up to 55°C	—	—	300	750	mW
T _A > 55°C	—	—	Derate at 6.67		mW/°C
T _A up to 75°C	300	750	—	—	mW
T _A > 75°C	Derate at 8		—	—	mW/°C
Collector-to-Emitter Voltage, V _{CE0}	15	—	15	—	V
Collector-to-Base Voltage, V _{CB0}	20	—	20	—	V
Collector-to-Substrate Voltage, V _{CIO} *	20	—	20	—	V
Emitter-to-Base Voltage, V _{EBO}	5	—	5	—	V
Collector Current	50	—	50	—	mA
Temperature Range:					
Operating	-55 to +125		-55 to +125		°C
Storage	-65 to +150		-65 to +150		°C
Lead Temperature (During Soldering):					
At distance 1/16 ± 1/32" (1.59 ± 0.79 mm)					
from case for 10 seconds max.		+265		+265	°C

* The collector of each transistor of the CA3045 and CA3046 is isolated from the substrate by an integral diode. The substrate (terminal 13) must be connected

to the most negative point in the external circuit to maintain isolation between transistors and to provide for normal transistor action.

ELECTRICAL CHARACTERISTICS, at T_A = 25°C

Characteristics apply for each transistor in the CA3045 and CA3046 as specified.

CHARACTERISTICS	SYMBOLS	SPECIAL TEST CONDITIONS	LIMITS			UNITS	CHARACTERISTIC CURVES
			Type CA3045 Type CA3046				
			MIN.	TYP.	MAX.		FIG.
STATIC CHARACTERISTICS							
Collector-to-Base Breakdown Voltage	V _{(BR)CB0}	I _C = 10 μA, I _E = 0	20	60	-	V	-
Collector-to-Emitter Breakdown Voltage	V _{(BR)CE0}	I _C = 1 mA, I _B = 0	15	24	-	V	-
Collector-to-Substrate Breakdown Voltage	V _{(BR)CIO}	I _C = 10 μA, I _{C1} = 0	20	60	-	V	-
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E = 10 μA, I _C = 0	5	7	-	V	-
Collector-Cutoff Current	I _{CB0}	V _{CB} = 10 V, I _E = 0	-	0.002	40	nA	2
Collector-Cutoff Current	I _{CE0}	V _{CE} = 10 V, I _B = 0	-	See curve	0.5	μA	3
Static Forward Current-Transfer Ratio (Static Beta)	h _{FE}	V _{CE} = 3 V { I _C = 10 mA I _C = 1 mA I _C = 10 μA	-	100	-	-	4
Input Offset Current for Matched Pair Q ₁ and Q ₂ . I _{O1} - I _{O2}		V _{CE} = 3 V, I _C = 1 mA	-	0.3	2	μA	5
Base-to-Emitter Voltage	V _{BE}	V _{CE} = 3 V { I _E = 1 mA I _E = 10 mA	-	0.715	-	V	6
Magnitude of Input Offset Voltage for Differential Pair V _{BE1} - V _{BE2}		V _{CE} = 3 V, I _C = 1 mA	-	0.45	5	mV	6, 8
Magnitude of Input Offset Voltage for Isolated Transistors V _{BE3} - V _{BE4} , V _{BE4} - V _{BE5} , V _{BE5} - V _{BE3}		V _{CE} = 3 V, I _C = 1 mA	-	0.45	5	mV	6, 8
Temperature Coefficient of Base-to-Emitter Voltage	$\frac{\Delta V_{BE}}{\Delta T}$	V _{CE} = 3 V, I _C = 1 mA	-	-1.9	-	mV/°C	7
Collector-to-Emitter Saturation Voltage	V _{CES}	I _B = 1 mA, I _C = 10 mA	-	0.23	-	V	-
Temperature Coefficient: Magnitude of Input-Offset Voltage	$\frac{ \Delta V_{IO} }{\Delta T}$	V _{CE} = 3 V, I _C = 1 mA	-	1.1	-	μV/°C	8

Linear Integrated Circuits

CA3045, CA3046 Types

ELECTRICAL CHARACTERISTICS (Cont'd.)

DYNAMIC CHARACTERISTICS							
Low-Frequency Noise Figure	NF	$f = 1 \text{ kHz}, V_{CE} = 3 \text{ V}, I_C = 100 \mu\text{A}$ Source Resistance = $1 \text{ k}\Omega$	-	3.25	-	dB	9(b)
Low-Frequency, Small-Signal Equivalent-Circuit Characteristics:							
Forward Current-Transfer Ratio	h_{fe}	$f = 1 \text{ kHz}, V_{CE} = 3 \text{ V}, I_C = 1 \text{ mA}$	-	110	-	-	10
Short-Circuit Input Impedance	h_{ie}		-	3.5	-	$\text{k}\Omega$	
Open-Circuit Output Impedance	h_{oe}		-	15.6	-	μmho	
Open-Circuit Reverse Voltage-Transfer Ratio	h_{re}		-	1.8×10^{-4}	-	-	
Admittance Characteristics:							
Forward Transfer Admittance	Y_{fe}	$f = 1 \text{ MHz}, V_{CE} = 3 \text{ V}, I_C = 1 \text{ mA}$	-	$31 - j1.5$	-	-	11
Input Admittance	Y_{ie}		-	$0.3 + j0.04$	-	-	12
Output Admittance	Y_{oe}		-	$0.001 + j0.03$	-	-	13
Reverse Transfer Admittance	Y_{re}		-	See curve	-	-	14
Gain-Bandwidth Product	f_T	$V_{CE} = 3 \text{ V}, I_C = 3 \text{ mA}$	300	550	-	-	15
Emitter-to-Base Capacitance	C_{EB}	$V_{EB} = 3 \text{ V}, I_E = 0$	-	0.6	-	pF	-
Collector-to-Base Capacitance	C_{CB}	$V_{CB} = 3 \text{ V}, I_C = 0$	-	0.58	-	pF	-
Collector-to-Substrate Capacitance	C_{CI}	$V_{CS} = 3 \text{ V}, I_C = 0$	-	2.8	-	pF	-

STATIC CHARACTERISTICS

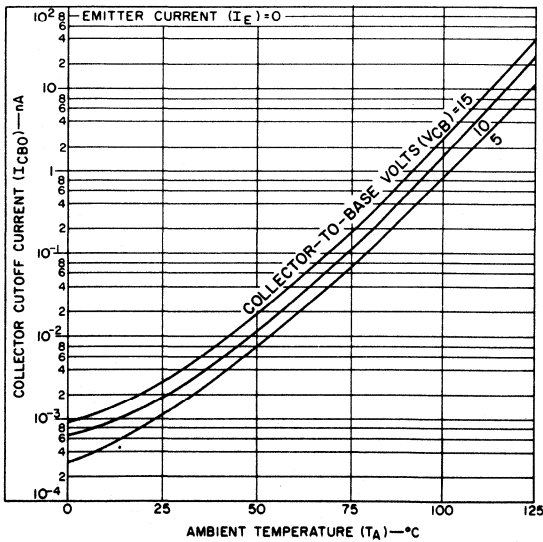


Fig. 2 - Typical collector-to-base cutoff current vs ambient temperature for each transistor.

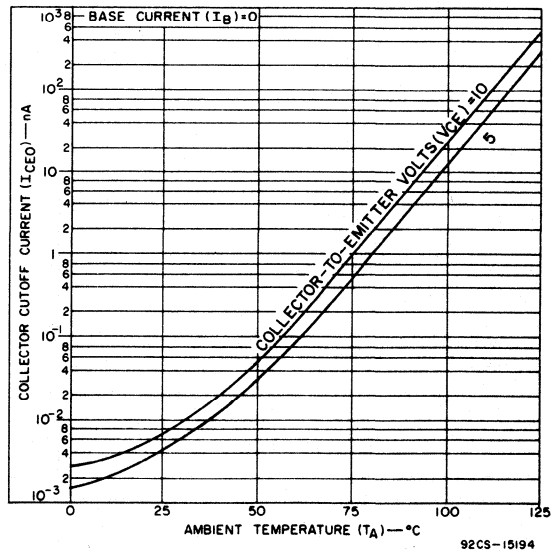


Fig. 3 - Typical collector-to-emitter cutoff current vs ambient temperature for each transistor.

STATIC CHARACTERISTICS

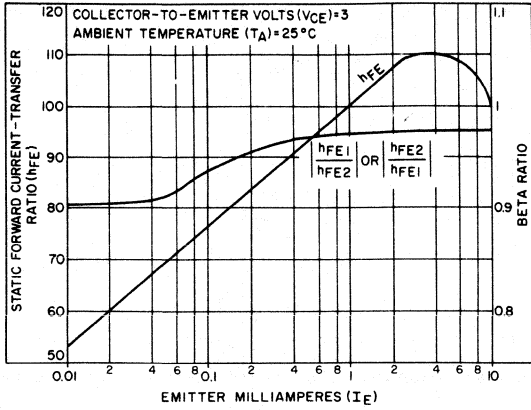


Fig. 4 - Typical static forward current-transfer ratio and beta ratio for transistors Q_1 and Q_2 vs emitter current.

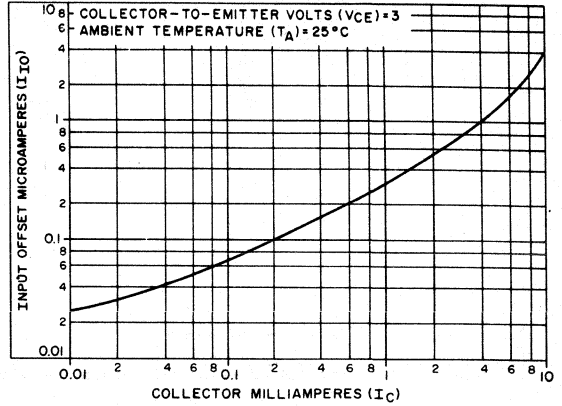


Fig. 5 - Typical input offset current for matched transistor pair Q_1Q_2 vs collector current.

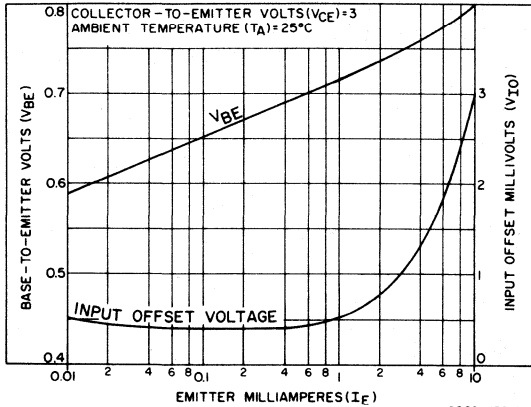


Fig. 6 - Typical static base-to-emitter voltage characteristic and input offset voltage for differential pair and paired isolated transistors vs emitter current.

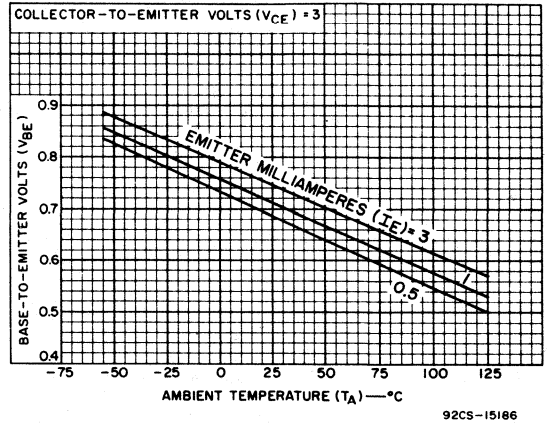


Fig. 7 - Typical base-to-emitter voltage characteristic vs ambient temperature for each transistor.

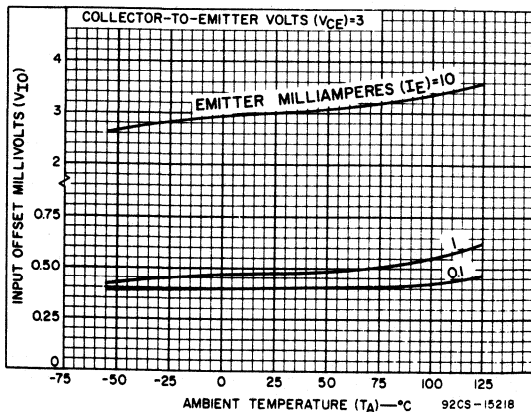


Fig. 8 - Typical input offset voltage characteristics for differential pair and paired isolated transistors vs ambient temperature.

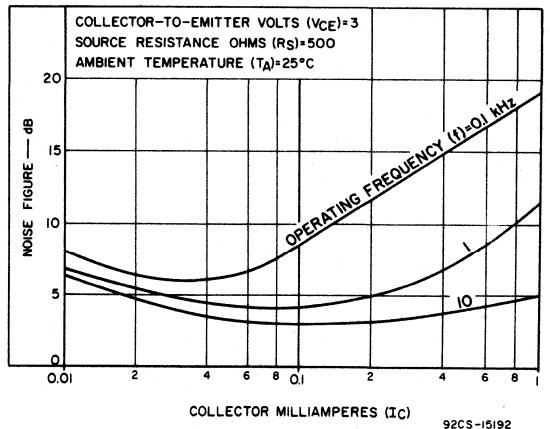


Fig. 9(a) - Typical noise figure vs collector current.

Linear Integrated Circuits

CA3045, CA3046 Types

DYNAMIC CHARACTERISTICS FOR EACH TRANSISTOR

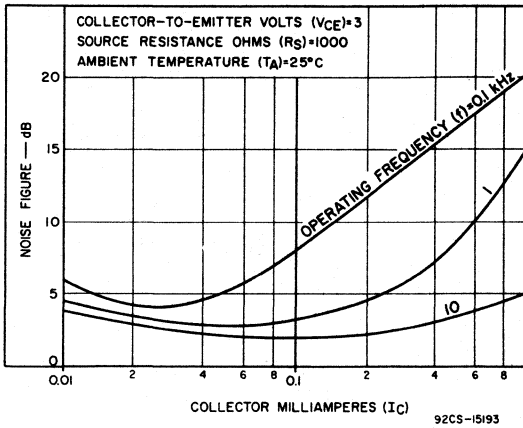


Fig.9(b) - Typical noise figure vs collector current.

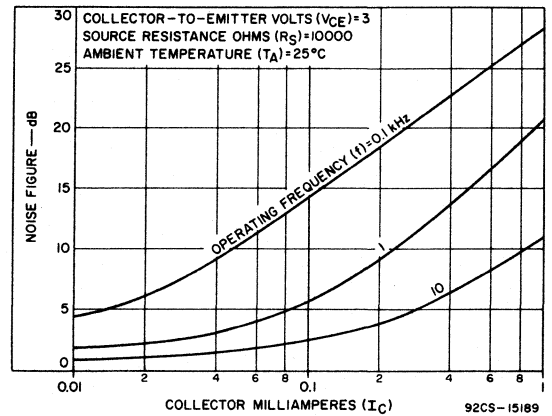


Fig.9(c) - Typical noise figure vs collector current.

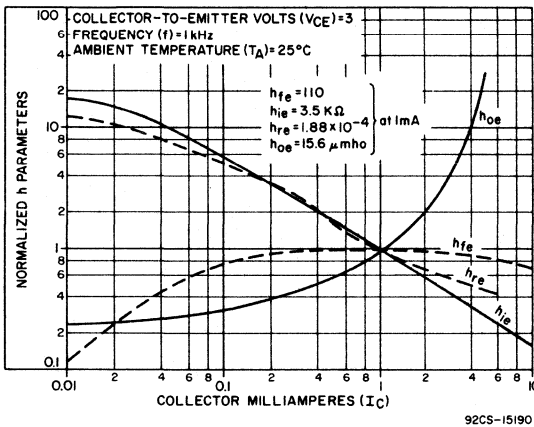


Fig.10 - Typical normalized forward current-transfer ratio, short-circuit input impedance, open-circuit output impedance, and open-circuit reverse voltage-transfer ratio vs collector current.

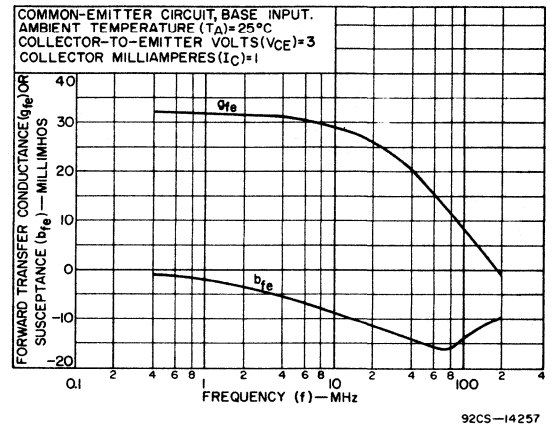


Fig.11 - Typical forward transfer admittance vs frequency.

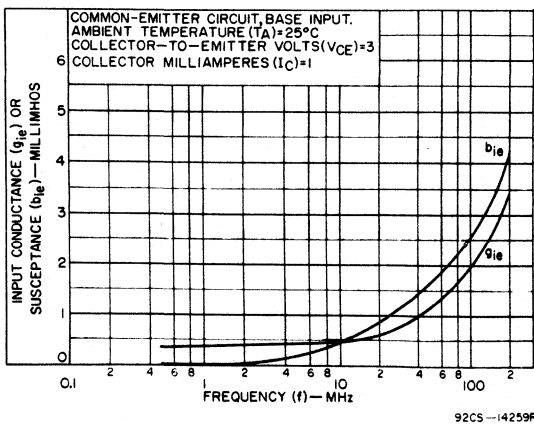


Fig.12 - Typical input admittance vs frequency.

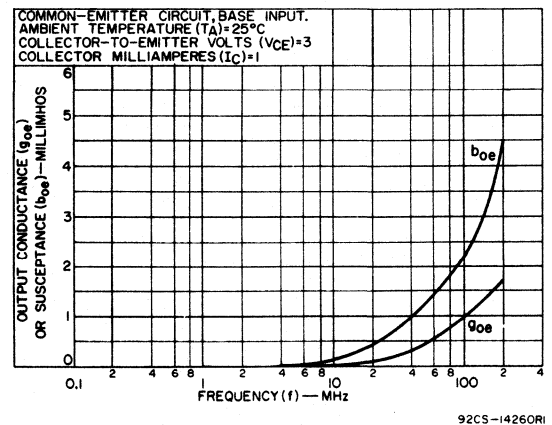


Fig.13 - Typical output admittance vs frequency.

CA3045, CA3046 Types

DYNAMIC CHARACTERISTICS FOR EACH TRANSISTOR

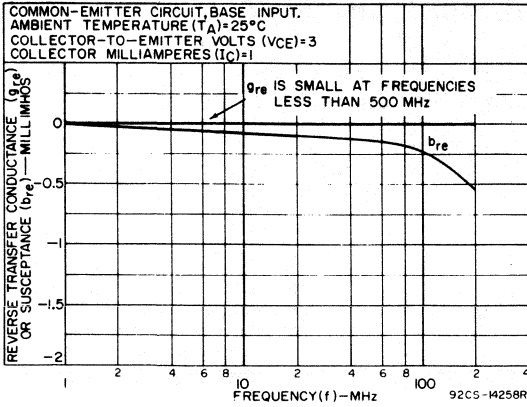


Fig.14 - Typical reverse transfer admittance vs frequency.

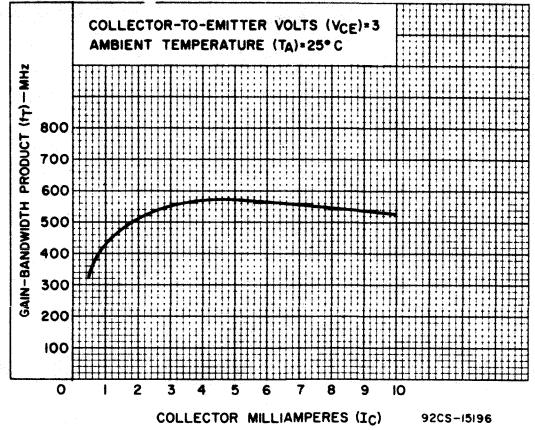
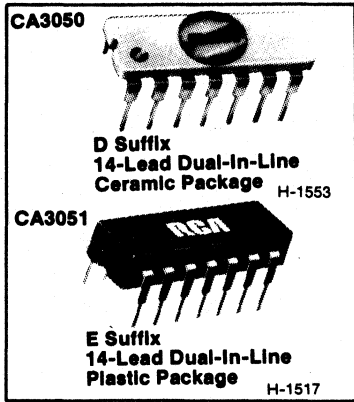


Fig.15 - Typical gain-bandwidth product vs collector current.

CA3050, CA3051



Dual Differential Amplifiers

Two Darling-ton-Connected Differential Amplifiers with Diode Bias String
 For Low-Power Applications at Frequencies from DC to 20 MHz

Features:

- Input offset current - 70 nA max.
- Input bias current - 500 nA max.
- Input offset voltage - 5 mV max.
- Input impedance - 460 kΩ typ.
- Independently accessible inputs and outputs

Applications

- Matched dual amplifiers
- Dual sense amplifiers
- Dual Schmitt triggers
- Dual multivibrators
- Doubly balanced detectors and modulators
- Balanced quadrature detectors
- Synthesizer mixers
- Product detectors

The CA3050 and CA3051 each consists of two differential amplifiers with associated constant current transistors on a common substrate. Each amplifier is driven by Darling-ton-connected emitter follower inputs to provide high input impedance, low bias current, and low offset current. A string of diodes is included to provide temperature-compensated bias to the constant current transistors and a low impedance bias point for the inputs to the differential amplifiers when a single power supply is used.

The CA3050 is supplied in an hermetic 14-lead Dual-In-Line ceramic package rated for operation over the full military temperature range of -55°C to +125°C.

The CA3051 is supplied in a Dual-In-Line plastic package for applications requiring only a limited temperature range of -25°C to +85°C.

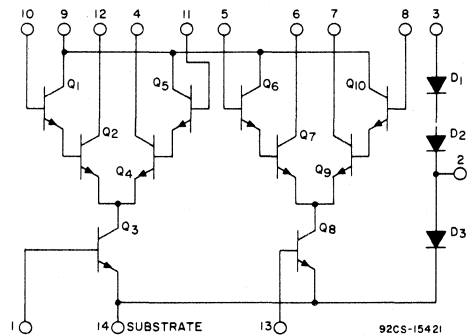


Fig. 1 - Schematic diagram.

CA3050, CA3051

MAXIMUM RATINGS, ABSOLUTE-MAXIMUM VALUES, AT T_A = 25°C

	CA3050	CA3051	
Power Dissipation, P:			
Any one transistor	150	150	mW
Total package	900	750	mW
For T _A > 55°C, Derate at	8	6.67	mW/°C
Temperature Range:			
Operating	-55 to +125	-40 to +85	°C
Storage	-65 to +150	-65 to +150	°C
LEAD TEMPERATURE (During Soldering)			
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm)			
from case for 10 seconds max.			+265°C

The following ratings apply for each transistor in the device:

Collector-to-Emitter Voltage, V _{CEO}	15	V
Collector-to-Base Voltage, V _{CBO}	20	V
Collector-to-Substrate Voltage, V _{CIO} *	20	V
Emitter-to-Base Voltage, V _{EBO}	5	V
Collector Current, I _C	50	mA

* The collector of each transistor of the CA3050 and CA3051 is isolated from the substrate by an integral diode. The substrate (terminal 14) must be more negative than all col-

lectors to maintain isolation between transistors and to provide for normal transistor action.

MAXIMUM VOLTAGE RATINGS

The following chart gives the range of voltages which can be applied to the terminals listed vertically with respect to the terminals listed horizontally. For example, the voltage range between vertical terminal 2 and horizontal terminal 3 is +5 to -2 volts.

TERMINAL No.	1	2	3	4	5	6	7	8	9	10	11	12	13	14
1	-	*	*	*	*	*	*	*	*	*	*	*	*	+1 -5
2			+5 -2	*	*	*	*	*	*	*	*	*	*	+1 -1
3				*	*	*	*	*	*	*	*	*	*	+3 -1
4					*	*	*	*	*	-14 -2.5 Note 3	+14 -2.5 Note 4	*	*	+20 -1
5						+2.5 -14 Note 1	+2.5 -14 Note 1	+10 -10	+1 -20	*	*	*	*	+16 -
6							*	+14 -2.5 Note 2	*	*	*	*	*	+20 -1
7								+14 -2.5 Note 2	*	*	*	*	*	+20 -1
8									+1 20	*	*	*	*	+16 -
9										+20 -1	+20 -1	*	*	+20 -1
10											+10 -10	+2.5 -14 Note 3	*	+16 -
11												+2.5 -14 Note 4	*	+16 -
12														+20 -1
13														+1 -5
14														Ref. Substrate

Note 1: This rating is important only when terminal 5 is more positive than terminal 8.
 Note 2: This rating is important only when terminal 8 is more positive than terminal 5.
 Note 3: This rating is important only when terminal 10 is more positive than terminal 11.

Note 4: This rating is important only when terminal 11 is more positive than terminal 10.

* Voltages are not normally applied between these terminals. Voltages appearing between these terminals will be safe if the specified limits between all other terminals are not exceeded.

MAXIMUM CURRENT RATINGS

TERMINAL No.	I _{IN} mA	I _{OUT} mA
1	5	0.1
2	50	50
3	50	1
4	50	1
5	5	0.1
6	50	1
7	50	1
8	5	0.1
9	50	1
10	5	0.1
11	5	0.1
12	50	1
13	5	0.1
14	100	5

Linear Integrated Circuits

CA3050, CA3051

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

CHARACTERISTICS	SYMBOLS	TEST CONDITIONS	TEST CIRCUIT	LIMITS CA3050/CA3051			UNITS	TYPICAL CHARACTERISTICS CURVES
			FIG.	MIN.	TYP.	MAX.		FIG.
STATIC								
Amplifier Characteristics								
Input Offset Voltage	V_{IO}		-	-	1.5	5	mV	2a,b
Input Offset Current	I_{IO}		-	-	7	70	nA	3a,b
Input Bias Current	I_I		-	-	200	500	nA	4a,b
Quiescent Operating Current Ratio	$\frac{(I_4+I_{12})}{I_3}$ or $\frac{(I_6+I_7)}{I_3}$	$V_{CC} = +6\text{ V}, I_3 = 2\text{ mA}$	-	0.9	1.00	1.13	-	5a,b
DC Forward Base-to-Emitter Voltage	V_{BE}	$V_{CE} = 3\text{ V}$	-	-	0.645	0.700	V	6
		$I_C = 50\ \mu\text{A}$	-	-	0.725	0.800		
		1 mA	-	-	0.760	0.850		
		3 mA	-	-	0.805	0.900		
		10 mA	-	-				
Temperature Coefficient of Base-to-Emitter Voltage	$\frac{\Delta V_{BE}}{\Delta T}$	$V_{CE} = 3\text{ V}, I_C = 1\text{ mA}$	-	-	-1.9	-	mV/ $^\circ\text{C}$	7
Transistor Characteristics								
Collector-Cutoff Current	I_{CBO}	$V_{CB} = 10\text{ V}, I_E = 0$	-	-	0.002	100	nA	8
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 1\text{ mA}, I_B = 0$	-	15	24	-	V	-
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 10\ \mu\text{A}, I_E = 0$	-	20	60	-	V	-
Collector-to-Substrate Breakdown Voltage	$V_{(BR)CIO}$	$I_C = 10\ \mu\text{A}, I_{CI} = 0$	-	20	60	-	V	-
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 10\ \mu\text{A}, I_C = 0$	-	5	7	-	V	-
DYNAMIC								
Transistor Characteristics								
Emitter-to-Base Capacitance	C_{EB}	$V_{EB} = 3\text{ V}, I_E = 0$	-	-	0.78	-	pF	9
Collector-to-Base Capacitance	C_{CB}	$V_{CB} = 3\text{ V}, I_C = 0$	-	-	0.47	-	pF	9
Collector-to-Substrate Capacitance	C_{CI}	$V_{CS} = 3\text{ V}, I_C = 0$	-	-	1.92	-	pF	9
Amplifier Characteristics								
Gain-Bandwidth Product (For Single Transistor)	f_T	$V_{CE} = 5\text{ V}, I_C = 3\text{ mA}$	-	-	600	-	MHz	10
Forward Transadmittance (With single-ended input and output)	$ y_{21} $	$V_{CC} = 10\text{ V}, I_3 = 2\text{ mA}$ $f = 1\text{ MHz}$	11	7	9	11	mmho	11
Bandwidth at -3 dB Point	BW	$V_{CC} = 10\text{ V}, I_3 = 2\text{ mA}$	11	-	4.3	-	MHz	11
Input Impedance	Z_{IN}	$V_{CC} = 10\text{ V}, I_3 = 2\text{ mA}$ $f = 1\text{ KHz}$	12	-	460	-	k Ω	12
Output Impedance	Z_{OUT}	$I_3 = 2\text{ mA}, f = 1\text{ KHz}$	13	-	170	-	k Ω	13
Common-Mode Rejection Ratio	CMR	$I_3 = 2\text{ mA}, f = 1\text{ KHz}$	-	-	65	-	dB	-
AGC Range	AGC	$I_3 = 2\text{ mA}, f = 1\text{ KHz}$ Terminal No.3 Grounded	11	-	60	-	dB	-

TYPICAL STATIC CHARACTERISTICS

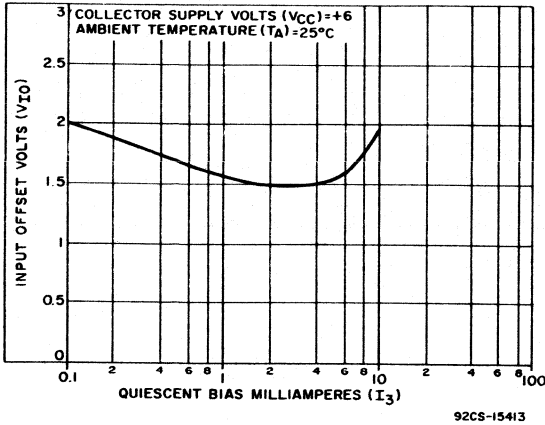


Fig.2(a) - Typical input offset voltage vs quiescent bias current.

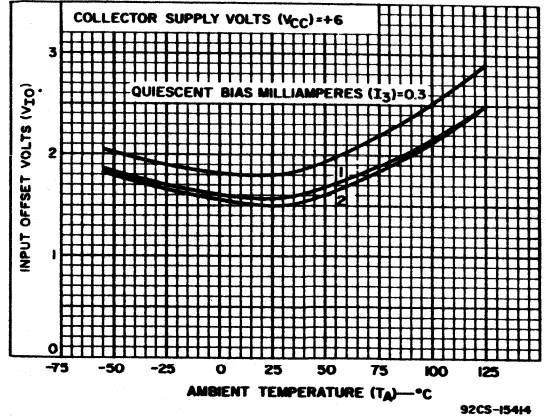


Fig.2(b) - Typical input offset voltage vs ambient temperature.

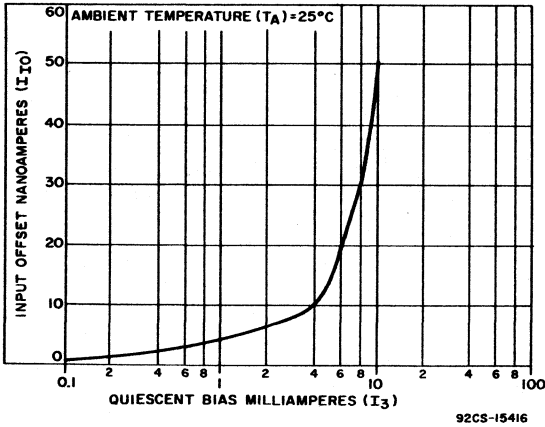


Fig.3(a) - Typical input offset current vs quiescent bias current.

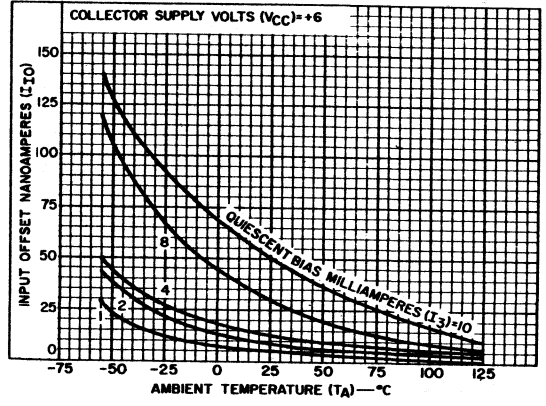


Fig.3(b) - Typical input offset current vs ambient temperature.

STATIC CHARACTERISTICS

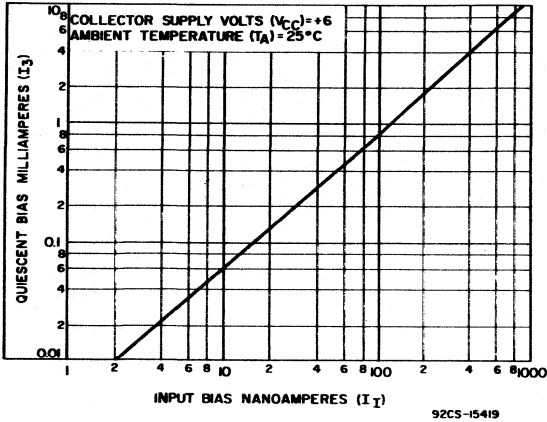


Fig.4(a) - Typical quiescent bias current vs input bias current.

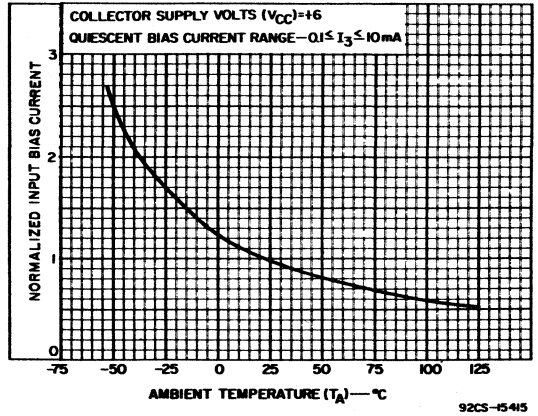


Fig.4(b) - Typical normalized input bias current vs ambient temperature.

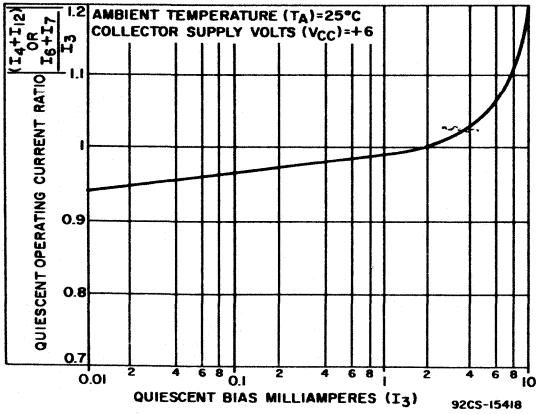


Fig.5(a) - Typical quiescent operating current ratio vs quiescent bias current.

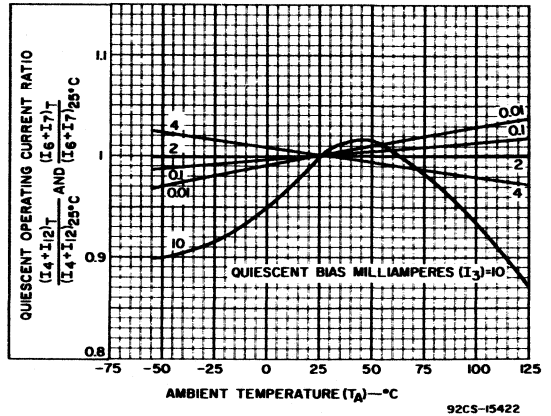


Fig.5(b) - Typical quiescent operating current ratio vs ambient temperature.

STATIC CHARACTERISTICS

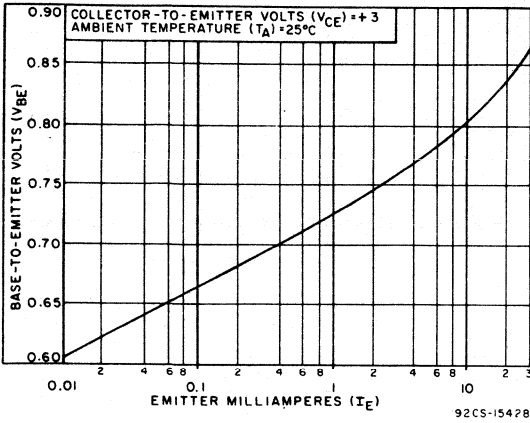


Fig.6 - Typical static base-to-emitter voltage characteristic vs emitter current for all transistors and forward diode voltage drops.

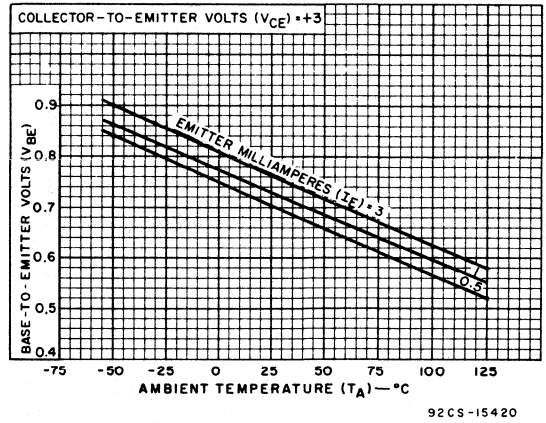


Fig.7 - Typical base-to-emitter voltage characteristic vs ambient temperature for each transistor.

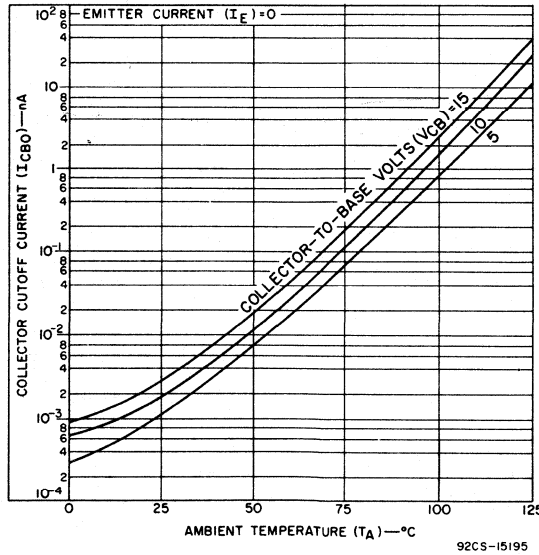


Fig.8 - Typical collector-to-base cutoff current vs ambient temperature for each transistor.

Linear Integrated Circuits

CA3050, CA3051

DYNAMIC CHARACTERISTICS FOR EACH TRANSISTOR

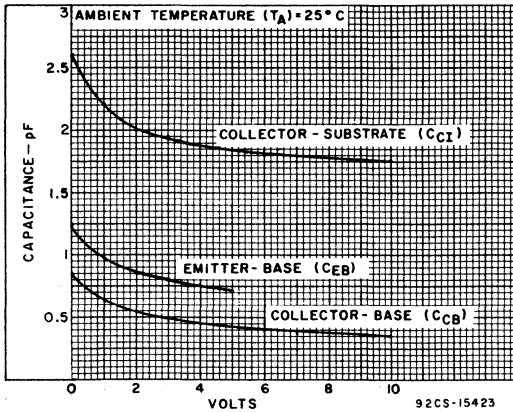


Fig.9 - Typical capacitance for each transistor.

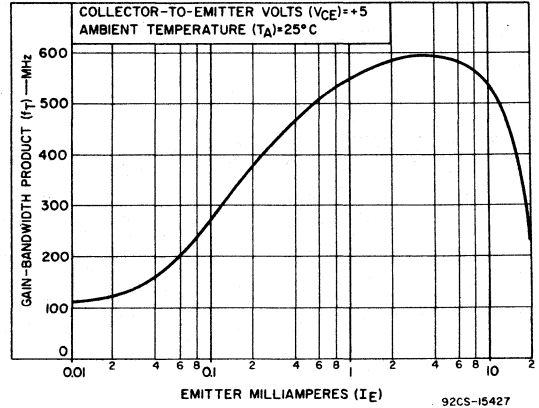
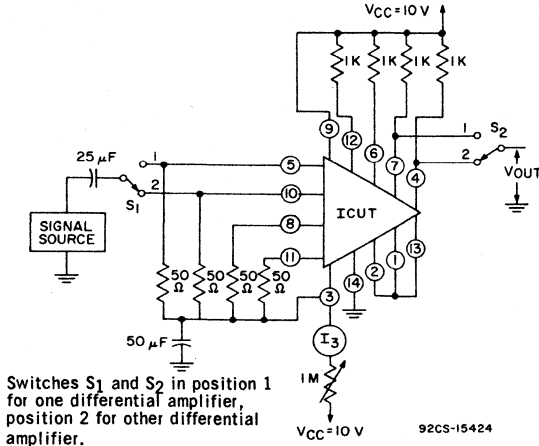


Fig.10 - Typical gain-bandwidth product (f_T) for each transistor vs emitter current.



Switches S_1 and S_2 in position 1 for one differential amplifier, position 2 for other differential amplifier.

Fig.11(a) - Test circuit for forward transadmittance, -3 dB bandwidth, and AGC range.

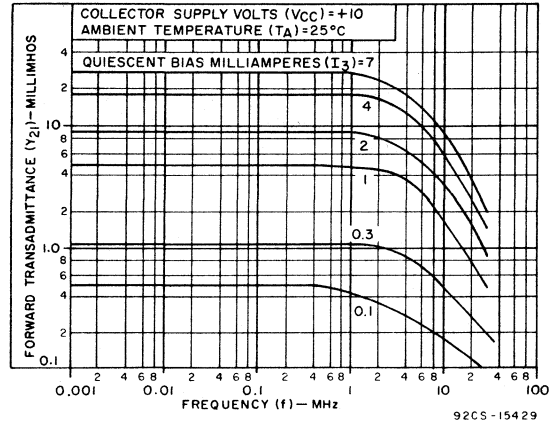


Fig.11(b) - Typical differential amplifier forward transadmittance with single-ended output vs frequency.

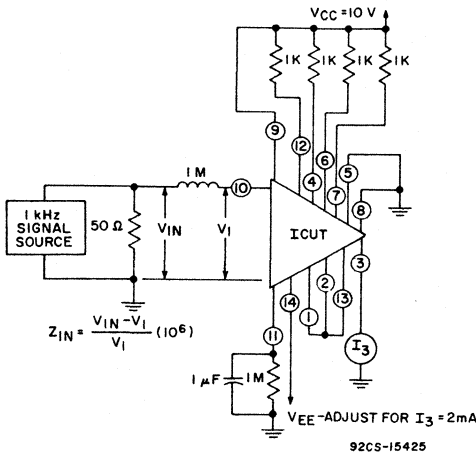


Fig.12(a) - Test circuit for input impedance.

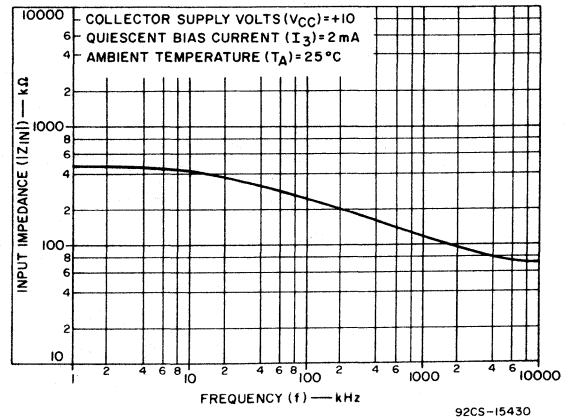
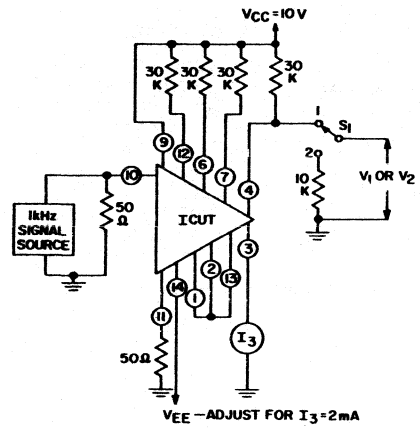


Fig.12(b) - Typical input impedance vs frequency with output short-circuited.

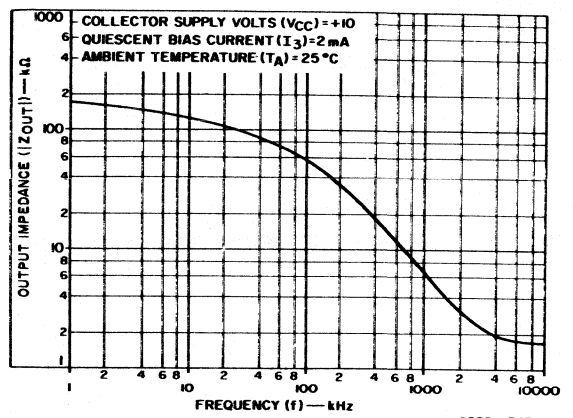
DYNAMIC CHARACTERISTICS FOR EACH TRANSISTOR



$$Z_{OUT} = \frac{(30K + 10K) \frac{V_2}{V_1}}{\frac{V_2}{V_1} (30K + 10K) - 10K}$$

92CS-15426

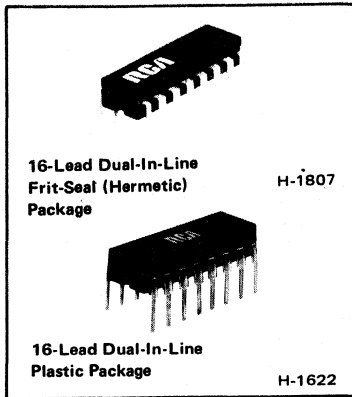
Fig.13(a) - Test circuit for output impedance.



92CS-15431

Fig.13(b) - Typical output impedance vs frequency with input short-circuited.

CA3083



General-Purpose High-Current N-P-N Transistor Array

Features:

- High I_C : 100 mA max.
- Low V_{CEsat} (at 50 mA): 0.7V max.
- Matched pair (Q1 and Q2) - V_{IO} (V_{BE} matched): ± 5 mV max. I_{IO} (at 1 mA): 2.5 μ A max.
- 5 independent transistors plus separate substrate connection

Applications:

- Signal processing and switching systems operating from DC to VHF
- Lamp and relay driver
- Differential amplifier
- Temperature-compensated amplifier
- Thyristor firing
- See RCA Application Note, ICAN-5296 "Application of the RCA-CA3018 Circuit Transistor Array" for suggested applications

RCA-CA3083 is a versatile array of five high-current (to 100mA) n-p-n transistors on a common monolithic substrate. In addition, two of these transistors (Q1 and Q2) are matched at low currents (i.e. 1 mA) for applications in which offset parameters are of special importance.

Independent connections for each transistor plus a separate terminal for the substrate permit maximum flexibility in circuit design. The CA3083 is supplied in a 16-lead dual-in-line frit-seal ceramic package. The CA3083 is also available in chip form.

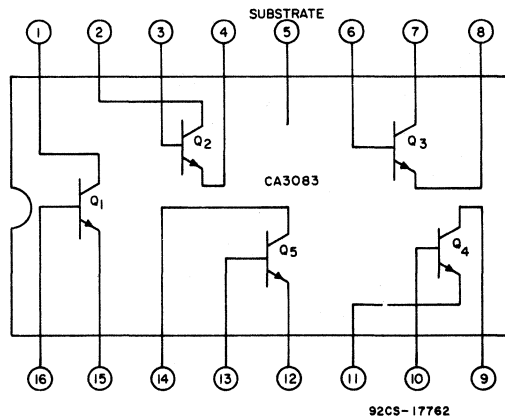


Fig. 1 — Functional diagram of the CA3083.

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

Power Dissipation:

Any one transistor	500	mW
Total package	750	mW
Above 55°C	Derate linearly 6.67	mW/ $^\circ\text{C}$

Ambient Temperature Range:

Operating	-55 to $+125$	$^\circ\text{C}$
Storage	-65 to $+150$	$^\circ\text{C}$

Lead Temperature (During Soldering):

At distance $1/16'' \pm 1/32''$ ($1.59 \text{ mm} \pm 0.79 \text{ mm}$)		
from case for 10 seconds max.	265	$^\circ\text{C}$

The following ratings apply for each transistor in the device:

Collector-to-Emitter Voltage (V_{CEO})	15	V
Collector-to-Base Voltage (V_{CBO})	20	V
Collector-to-Substrate Voltage (V_{C1O}) [■]	20	V
Emitter-to-Base Voltage (V_{EBO})	5	V
Collector Current (I_{C})	100	mA
Base Current (I_{B})	20	mA

[■] The collector of each transistor of the CA3083 is isolated from the substrate by an integral diode. The substrate must be connected to a voltage which is more negative than any collector voltage in order to maintain isolation between transistors and provide normal transistor action. To avoid undesired coupling between transistors, the substrate terminal (5) should be maintained at either DC or signal (AC) ground. A suitable bypass capacitor can be used to establish a signal ground.

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$
For Equipment Design

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	LIMITS			UNITS	
			Min.	Typ.	Max.		
For Each Transistor:							
Collector-to-Base Breakdown Voltage	$V_{(\text{BR})\text{CBO}}$	$I_{\text{C}} = 100\mu\text{A}, I_{\text{E}} = 0$	—	20	60	—	V
Collector-to-Emitter Breakdown Voltage	$V_{(\text{BR})\text{CEO}}$	$I_{\text{C}} = 1\text{mA}, I_{\text{B}} = 0$	—	15	24	—	V
Collector-to-Substrate Breakdown Voltage	$V_{(\text{BR})\text{C1O}}$	$I_{\text{C1}} = 100\mu\text{A}, I_{\text{B}} = 0, I_{\text{E}} = 0$	—	20	60	—	V
Emitter-to-Base Breakdown Voltage	$V_{(\text{BR})\text{EBO}}$	$I_{\text{E}} = 500\mu\text{A}, I_{\text{C}} = 0$	—	5	6.9	—	V
Collector-Cutoff-Current	I_{CEO}	$V_{\text{CE}} = 10\text{V}, I_{\text{B}} = 0$	—	—	—	10	μA
Collector-Cutoff-Current	I_{CBO}	$V_{\text{CB}} = 10\text{V}, I_{\text{E}} = 0$	—	—	—	1	μA
DC Forward-Current Transfer Ratio	h_{FE}	$V_{\text{CE}} = 3\text{V}$ $I_{\text{C}} = 10\text{mA}$ $I_{\text{C}} = 50\text{mA}$	2	40	76	—	
Base-to-Emitter Voltage	V_{BE}	$V_{\text{CE}} = 3\text{V}, I_{\text{C}} = 10\text{mA}$	3	0.65	0.74	0.85	V
Collector-to-Emitter Saturation Voltage	V_{CEsat}	$I_{\text{C}} = 50\text{mA}, I_{\text{B}} = 5\text{mA}$	4	—	0.40	0.70	V
Gain-Bandwidth Product	f_{T}	$V_{\text{CE}} = 3\text{V}$ $I_{\text{C}} = 10\text{mA}$		—	450	—	MHz
For Transistors Q1 and Q2 (As a Differential Amplifier):							
Absolute Input Offset Voltage	$ V_{\text{IO}} $	$V_{\text{CE}} = 3\text{V}, I_{\text{C}} = 1\text{mA}$	7	—	1.2	5	mV
Absolute Input Offset Current	$ I_{\text{IO}} $		8	—	0.7	2.5	μA

TYPICAL STATIC CHARACTERISTICS FOR EACH TRANSISTOR

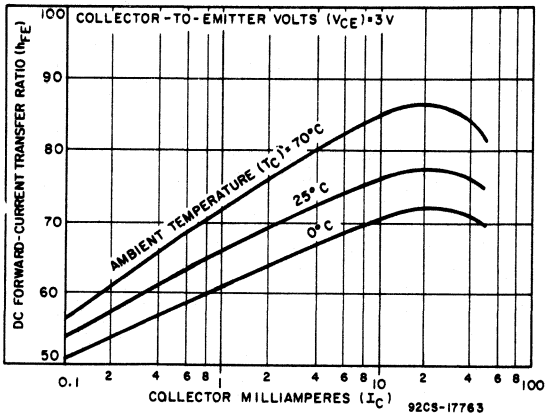


Fig. 2 - h_{FE} vs I_C

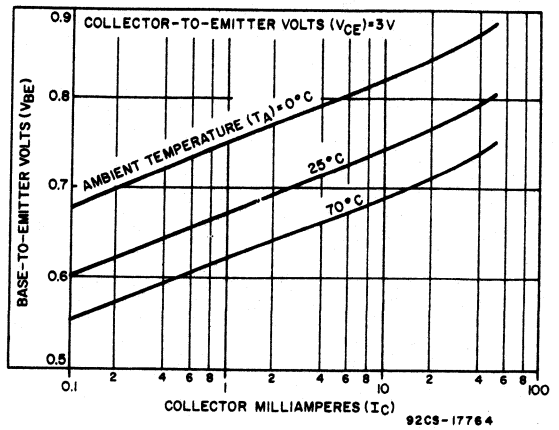


Fig. 3 - V_{BE} vs I_C

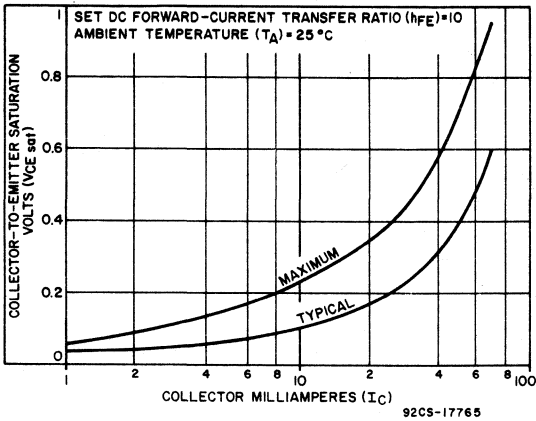


Fig. 4 - V_{CEsat} vs I_C at 25°C

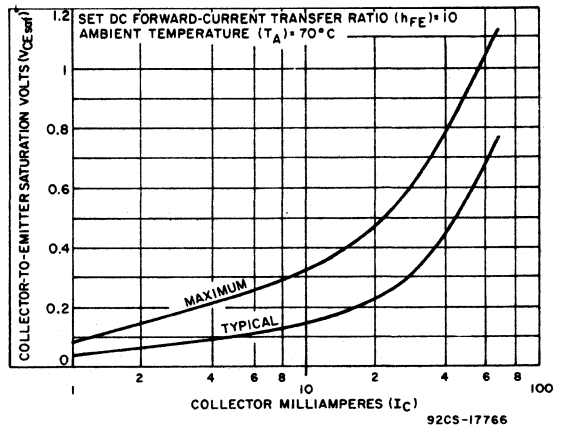


Fig. 5 - V_{CEsat} vs I_C at 70°C

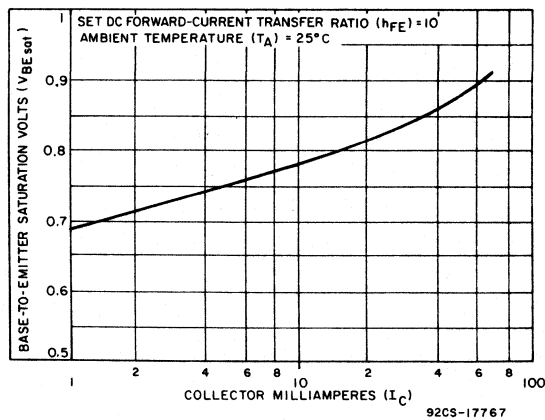


Fig. 6 - V_{BEsat} vs I_C

TYPICAL STATIC CHARACTERISTICS FOR DIFFERENTIAL AMPLIFIER

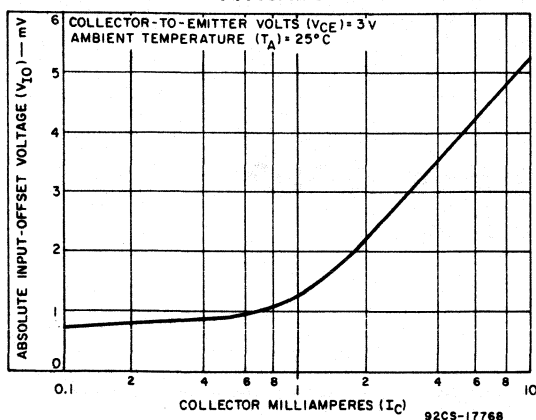


Fig.7 — V_{10} vs I_C (transistors Q1 and Q2 as a differential amplifier).

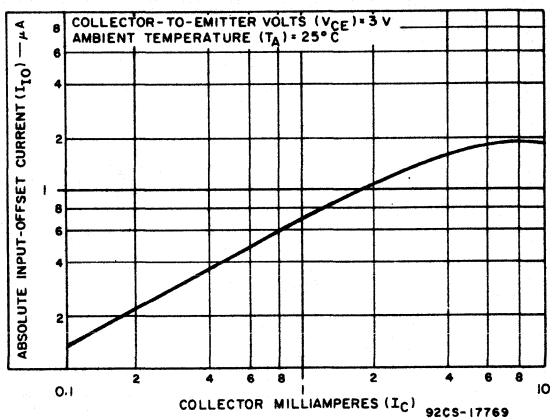
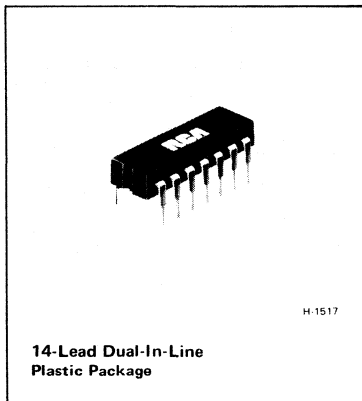


Fig.8 — I_{10} vs I_C (transistors Q1 and Q2 as a differential amplifier).

CA3084



General-Purpose P-N-P Transistor Array

FEATURES

- Matched transistor pair (Q1 and Q2)
 - V_{IO} (V_{BE} matched): $\pm 6mV$ max.
 - I_{IO} (at $100 \mu A$): $\pm 0.6 \mu A$
- Wide operating current range
- Low noise figure - - 3.2 dB typ. at 1 kHz

RCA-CA3084* is a general-purpose silicon p-n-p transistor array incorporating two independent transistors, a Darlington circuit, and a current-mirror pair with a shared diode.

The two independent transistors in the array may be used in a variety of circuit applications. The Darlington pair may be employed as the equivalent of a single high-beta transistor. The current-mirror pair is well suited for constant-current applications and can also be used as the active loads in a differential amplifier which uses n-p-n transistors.

The total array is especially useful for a wide range of applications in systems having low-power and low-frequency requirements. Although the transistors may be used as discrete units in conventional circuits, they offer the advantages inherent in integrated-circuit construction, that is, to provide close electrical and thermal matching.

The CA3084 utilizes the 14-lead dual-in-line plastic package.

*Formerly developmental type TA5799A.

APPLICATIONS

- General use in signal processing systems having low-power and low-frequency requirements
- Differential amplifiers
- Temperature compensated amplifiers
- Active loads for differential amplifiers using n-p-n transistors
- Complementary uses with RCA n-p-n transistor arrays

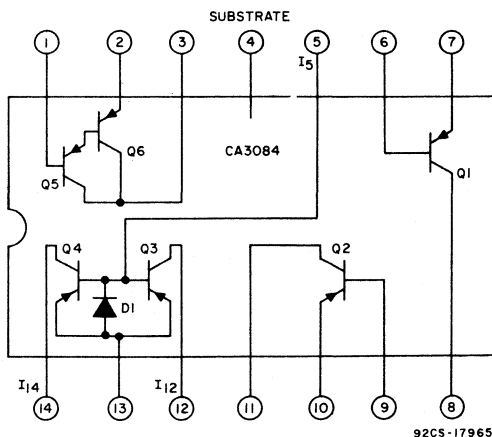


Fig.1 - Functional diagram of the CA3084.

ELECTRICAL CHARACTERISTICS at T_A = 25°C
For Equipment Design

CHARACTERISTICS	SYMBOL	TEST CONDITIONS		LIMITS			UNITS
			Typ. Characteristics Curve Fig. No.	Min.	Typ.	Max.	
For Each Transistor:							
Collector-Cutoff Current	I _{CBO}	V _{CB} = -10V, I _E = 0	2	-	-0.055	-100	nA
Collector-Cutoff Current	I _{CEO}	V _{CE} = -10V, I _B = 0	3	-	-0.12	-100	nA
Collector-to-Emitter Breakdown Voltage	V _{(BR)CEO}	I _{CE} = -100μA, I _B = 0	-	-40	-70	-	V
Collector-to-Base Breakdown Voltage	V _{(BR)CBO}	I _{CB} = -100μA, I _E = 0	-	-40	-80	-	V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _{EB} = -100μA, I _C = 0	-	-40	-100	-	V
Emitter-to-Substrate Breakdown Voltage	V _{(BR)EIO}	I _{EI} = 100μA	-	-40	-100	-	V
Collector-to-Emitter Saturation Voltage	V _{CEsat}	I _E = 1mA, I _B = 100μA	4	-	-0.125	-0.25	V
Base-to-Emitter Voltage	V _{BE}	I _E = 100μA, V _{CE} = -10V	5	-0.50	-0.59	-0.68	V
DC Forward-Current Transfer Ratio	h _{FE}		7	15	40	-	
For Transistors Q1 and Q2 (As a Differential Amplifier):							
Magnitude of Input Offset Voltage	V _{IO}	I _E = 100μA, V _{CE} = -10V	8	-	0.422	6	mV
Input Offset Current	I _{IO}		-	-0.6	0	0.6	μA
For Transistors Q3 and Q4 (Current-Mirror Configuration):							
Collector Current	I _C	V _{CE} = -10V, V _{CIO} = -10V,	10	0.85	1.00	1.15	μA
Magnitude of Collector Current Ratio	I _{C(Q3)} /I _{C(Q4)}	Term. 13 = Gnd. I _B = -100μA,	11	0.90	1.00	1.10	
For Transistors Q5 and Q6 (Darlington Configuration):							
Collector-Cutoff Current	I _{CEO}	V _{CE} = -10V, I _B = 0	-	-	-	-1.0	μA
Base-to-Emitter Voltage	V _{BE}	I _E = 100μA, V _{CE} = -10V	13	0.92	1.07	1.20	V
DC Forward-Current Transfer Ratio	h _{FE}		15	100	1230	-	

ELECTRICAL CHARACTERISTICS at T_A = 25°C
Typical Values Intended Only For Design Guidance

Magnitude of Temperature Coefficient:							
V _{BE} (for each transistor)	ΔV _{BE} /ΔT	I _E = 100μA,	6	-1.78			mV/°C
V _{IO} (as a differential amplifier)	ΔV _{IO} /ΔT		V _{CE} = -10V	9	0.54		
V _{BE} (Darlington configuration)	ΔV _{BE} /ΔT		14	-3.7			mV/°C
For Each Transistor:							
Input Resistance	R _I	f = 1kHz, V _{CE} = -10V,	19	9			kΩ
Output Resistance	R _O		I _C = -100μA	20	-	600	-
Forward Transconductance	g _m		22	-	3	-	mmho
Collector-to-Base Capacitance	C _{CBO}	I _{CB} = 0	23	-	3.3	-	pF
Collector-to-Emitter Capacitance	C _{CEO}	I _{CE} = 0	23	-	2.5	-	pF
Base-to-Substrate Capacitance	C _{BIO}	I _{CIO} = 0	23	-	4.5	-	pF

Linear Integrated Circuits

CA3084

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

Dissipation:

Any one transistor	200	mW
Total package	750	mW
Above $T_A = 55^\circ\text{C}$	derate linearly	6.67 mW/ $^\circ\text{C}$

Ambient Temperature Range:

Operating	-40 to +85	$^\circ\text{C}$
Storage	-55 to +150	$^\circ\text{C}$

The following ratings apply for each transistor in the device:

Collector-to-Emitter Voltage (V_{CEO})	-40	V
Collector-to-Base Voltage (V_{CBO})	-40	V
Base-to-Substrate Voltage (V_{BIO}) *	-40	V
Emitter-to-Base Voltage (V_{EBO})	-40	V
Collector Current (I_C)	-10	mA

*The base of each transistor of the CA3084 is isolated from the substrate by an integral diode. The substrate must be connected to a voltage which is more negative than any base voltage in order to maintain isolation between transistors and provide normal transistor action. To avoid undesired coupling between transistors, the substrate terminal (4) should be maintained at either DC or signal (AC) ground. A suitable bypass capacitor can be used to establish a signal ground.

STATIC CHARACTERISTICS FOR EACH TRANSISTOR

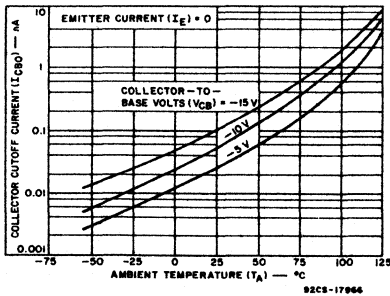


Fig.2— I_{CBO} vs T_A

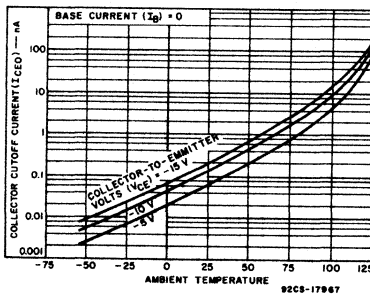


Fig.3— I_{CEO} vs T_A

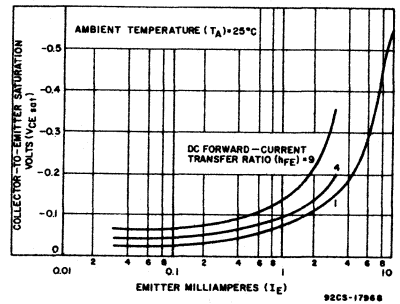


Fig.4— V_{CEsat} vs I_E

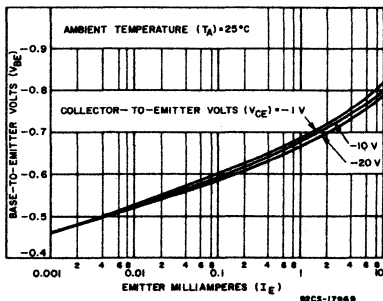


Fig.5— V_{BE} vs I_E

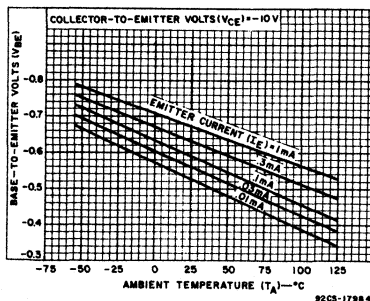


Fig.6— V_{BE} vs T_A

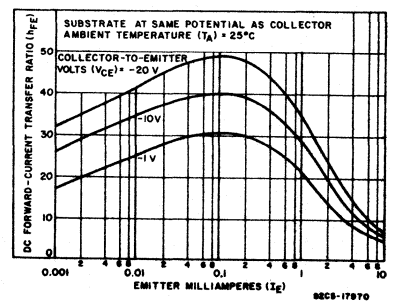


Fig.7— h_{FE} vs I_E

STATIC CHARACTERISTICS FOR DIFFERENTIAL AMPLIFIER

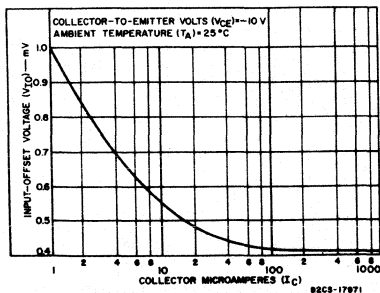


Fig.8— V_{IO} vs I_C (transistors Q1 and Q2 as a differential amplifier).

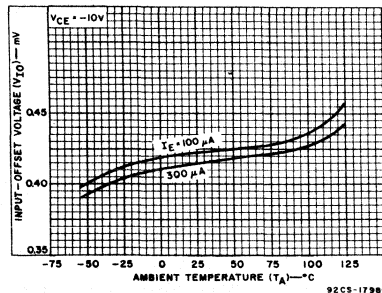


Fig.9— V_{IO} vs T_A (transistors Q1 and Q2 as a differential amplifier).

STATIC CHARACTERISTICS FOR CURRENT-MIRROR CONFIGURATION

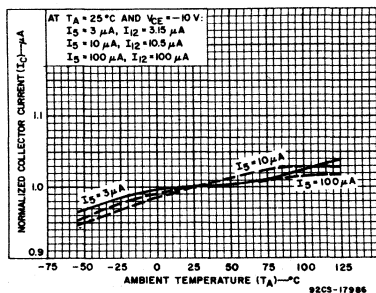


Fig.10—Normalized I_C vs T_A (transistors Q3 and Q4 in a current-mirror configuration).

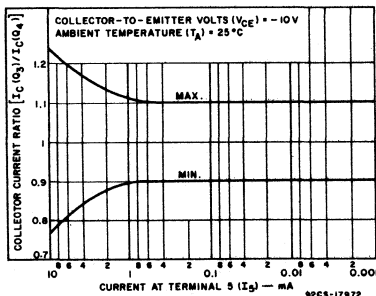


Fig.11— I_C ratio vs I_S (transistors Q3 and Q4 in a current-mirror configuration).

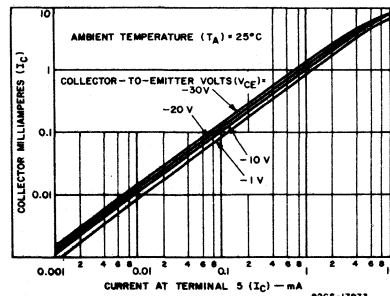


Fig.12— I_C vs I_S (transistors Q3 and Q4 in a current-mirror configuration).

STATIC CHARACTERISTICS FOR DARLINGTON CONFIGURATION

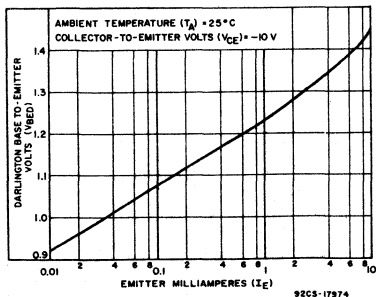


Fig.13— V_{BE} vs I_E (transistors Q5 and Q6 in a darlington configuration).

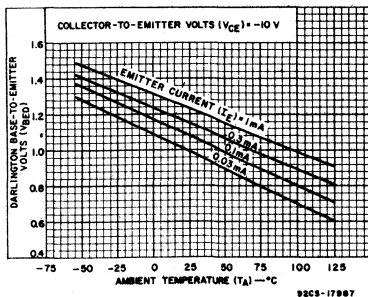


Fig.14— V_{BE} vs T_A (transistors Q5 and Q6 in a darlington configuration).

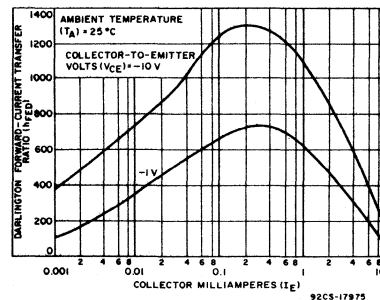


Fig.15— h_{FE} vs I_E (transistors Q5 and Q6 in a darlington configuration).

DYNAMIC CHARACTERISTICS FOR EACH TRANSISTOR

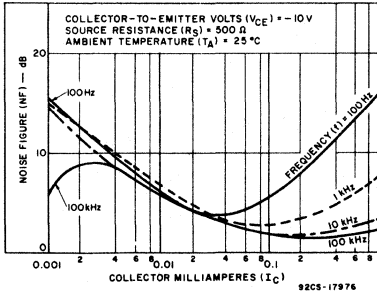


Fig. 16—NF vs I_C at $R_S = 500\Omega$

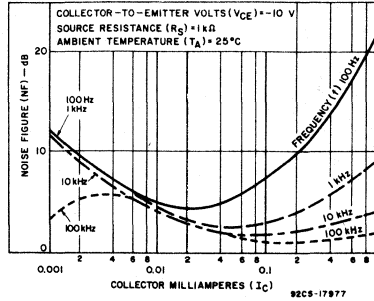


Fig. 17—NF vs I_C at $R_S = 1k\Omega$

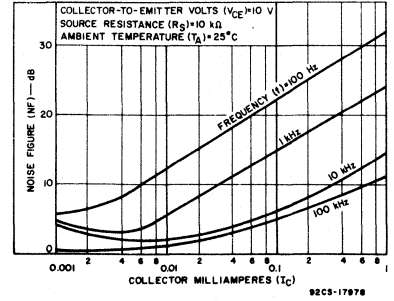


Fig. 18—NF vs I_C at $R_S = 10k\Omega$

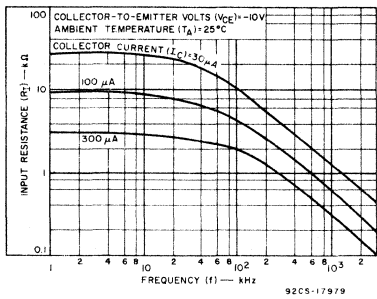


Fig. 19— R_i vs f

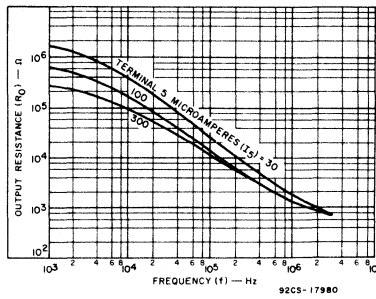


Fig. 20— R_o vs f

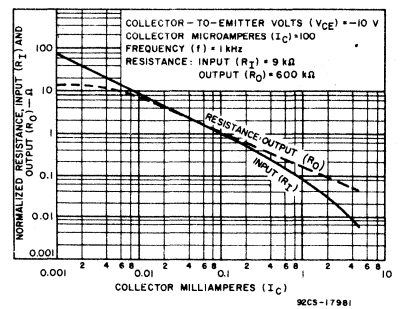


Fig. 21—Normalized R_i and R_o vs I_C

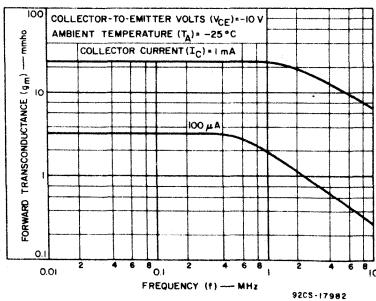


Fig. 22— g_m vs f

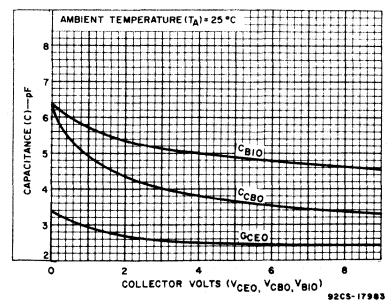
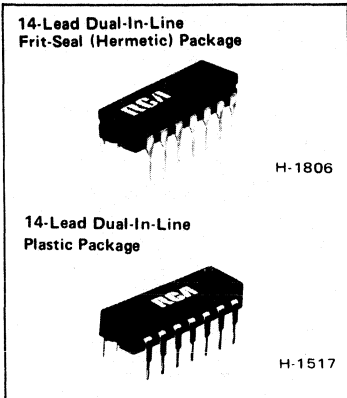


Fig. 23—Transistor capacitances vs collector voltages
(V_{CE0} , V_{CBO} , V_{C10})



General-Purpose N-P-N Transistor Array

Three Isolated Transistors and One Differentially-Connected Transistor Pair
For Low-Power Applications from DC to 120MHz

Applications

- General-purpose use in signal processing systems operating in the DC to 120-MHz range
- Temperature compensated amplifiers
- See RCA Application Note, ICAN-5296 "Application of the RCA-CA3018 Integrated-Circuit Transistor Array" for suggested applications.

RCA-CA3086 consists of five general-purpose silicon n-p-n transistors on a common monolithic substrate. Two of the transistors are internally connected to form a differentially-connected pair.

The transistors of the CA3086 are well suited to a wide variety of applications in low-power systems at frequencies from DC to 120 MHz. They may be used as discrete transistors in conventional circuits. However, they also provide the very significant inherent advantages unique to integrated circuits, such as compactness, ease of physical handling and thermal matching.

The CA3086 is supplied in a 14-lead dual-in line plastic package. The CA3086F is supplied in a 14-lead dual-in-line hermetic (frit-seal) ceramic package.

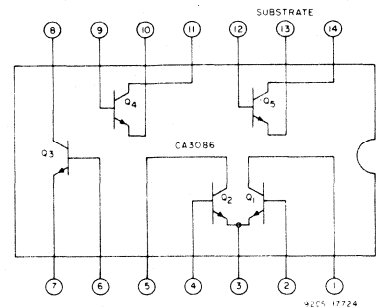


Fig. 1— Functional diagram of the CA3086.

MAXIMUM RATINGS, Absolute—Maximum Values at $T_A = 25^\circ\text{C}$

Dissipation:		
Any one transistor	300	mW
Total package up to $T_A = 55^\circ\text{C}$	750	mW
Above $T_A = 55^\circ\text{C}$	derate linearly 6.67	mW/ $^\circ\text{C}$
Ambient Temperature Range:		
Operating	-55 to + 125	$^\circ\text{C}$
Storage	-65 to + 150	$^\circ\text{C}$
Lead Temperature (During Soldering):		
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm)		
From case for 10 seconds max.....	+ 265	$^\circ\text{C}$
The following ratings apply for each transistor in the device:		
Collector-to-Emitter Voltage, V_{CEO}	15	V
Collector-to-Base Voltage, V_{CBO}	20	V
Collector-to-Substrate Voltage, V_{CISO}^*	20	V
Emitter-to-Base Voltage, V_{EBO}	5	V
Collector Current, I_C	50	mA

*The collector of each transistor in the CA3086 is isolated from the substrate by an integral diode. The substrate (terminal 13) must be connected to the most negative point in the external circuit to maintain isolation between transistors and to provide for normal transistor action. To avoid undesirable coupling between transistors, the substrate (terminal 13) should be maintained at either DC or signal (AC) ground. A suitable bypass capacitor can be used to establish a signal ground.

Linear Integrated Circuits

CA3086

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$
For Equipment Design

CHARACTERISTICS	SYMBOLS	TEST CONDITIONS		LIMITS			UNITS
			Typ. Characteristic Curves Fig. No.	Min.	Typ.	Max.	
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 10 \mu\text{A}, I_E = 0$	—	20	60	—	V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 1 \text{mA}, I_B = 0$	—	15	24	—	V
Collector-to-Substrate Breakdown Voltage	$V_{(BR)CIO}$	$I_C = 10 \mu\text{A}, I_{CI} = 0$	—	20	60	—	V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 10 \mu\text{A}, I_C = 0$	—	5	7	—	V
Collector-Cutoff Current	I_{CBO}	$V_{CB} = 10\text{V}, I_E = 0$	2	—	0.002	100	nA
Collector-Cutoff Current	I_{CEO}	$V_{CE} = 10\text{V}, I_B = 0$	3	—	See Curve	5	μA
DC Forward-Current Transfer Ratio	h_{FE}	$V_{CE} = 3\text{V}, I_C = 1 \text{mA}$	4	40	100	—	

TYPICAL STATIC CHARACTERISTICS FOR EACH TRANSISTOR

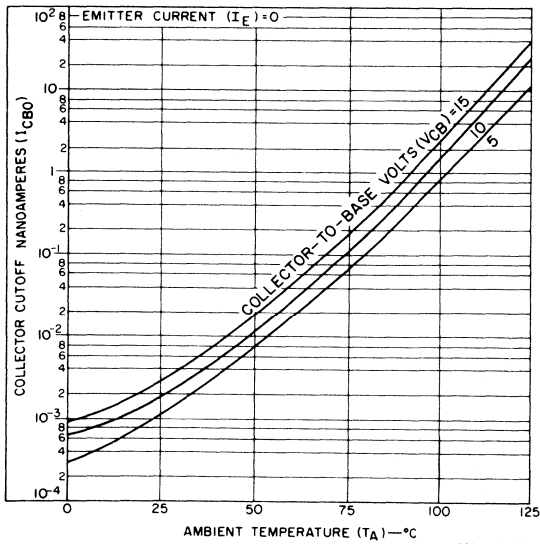


Fig.2— I_{CBO} vs T_A .

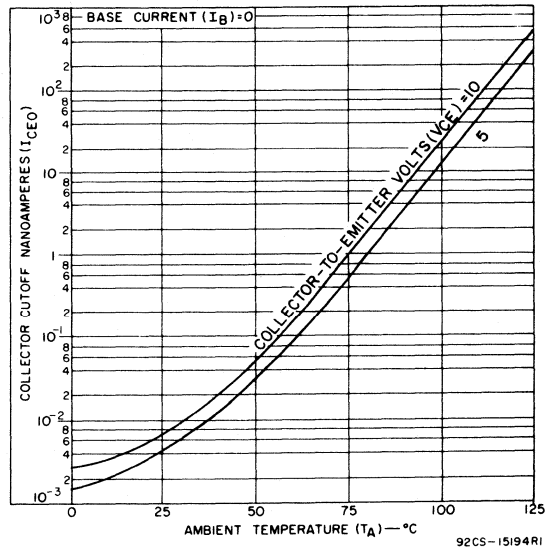


Fig.3— I_{CEO} vs T_A .

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$
Typical Values Intended Only for Design Guidance

CHARACTERISTICS	SYMBOL	TEST CONDITIONS			TYPICAL VALUES	UNITS
				Typ. Characteristics Curves Fig. No.		
DC Forward-Current Transfer Ratio	h_{FE}	$V_{CE} = 3\text{V}$	$I_C = 10\text{mA}$	4	100	
			$I_C = 10\mu\text{A}$	4	54	
Base-to-Emitter Voltage	V_{BE}	$V_{CE} = 3\text{V}$	$I_E = 1\text{mA}$	5	0.715	V
			$I_E = 10\text{mA}$	5	0.800	V
V_{BE} Temperature Coefficient	$\Delta V_{BE}/\Delta T$	$V_{CE} = 3\text{V}, I_C = 1\text{mA}$		6	-1.9	mV/ $^\circ\text{C}$
Collector-to-Emitter Saturation Voltage	V_{CEsat}	$I_B = 1\text{mA}, I_C = 10\text{mA}$		—	0.23	V
Noise Figure (low frequency)	NF	$f = 1\text{kHz}, V_{CE} = 3\text{V}, I_C = 100\mu\text{A}, R_S = 1\text{k}\Omega$		—	3.25	dB
Low-Frequency, Small-Signal Equivalent-Circuit Characteristics:						
Forward Current-Transfer Ratio	h_{fe}	$f = 1\text{kHz}, V_{CE} = 3\text{V}, I_C = 1\text{mA}$		7	100	—
Short-Circuit Input Impedance	h_{ie}			7	3.5	k Ω
Open-Circuit Output Impedance	h_{oe}			7	15.6	μmho
Open-Circuit Reverse-Voltage Transfer Ratio	h_{re}			7	1.8×10^{-4}	—
Admittance Characteristics:						
Forward Transfer Admittance	y_{fe}	$f = 1\text{MHz}, V_{CE} = 3\text{V}, I_C = 1\text{mA}$		8	$31 - j1.5$	mmho
Input Admittance	y_{ie}			9	$0.3 + j0.04$	mmho
Output Admittance	y_{oe}			10	$0.001 + j0.03$	mmho
Reverse Transfer Admittance	y_{re}			11	See Curve	—
Gain-Bandwidth Product	f_T	$V_{CE} = 3\text{V}, I_C = 3\text{mA}$		12	550	MHz
Emitter-to-Base Capacitance	C_{EBO}	$V_{EB} = 3\text{V}, I_E = 0$		—	0.6	pF
Collector-to-Base Capacitance	C_{CBO}	$V_{CB} = 3\text{V}, I_C = 0$		—	0.58	pF
Collector-to-Substrate Capacitance	C_{CIO}	$V_{CI} = 3\text{V}, I_C = 0$		—	2.8	pF

TYPICAL STATIC CHARACTERISTICS FOR EACH TRANSISTOR

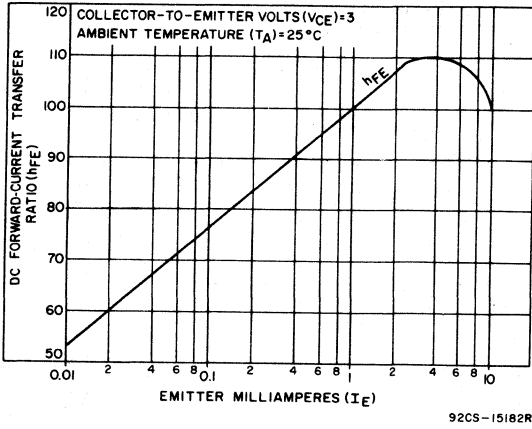


Fig.4 - h_{FE} vs I_E

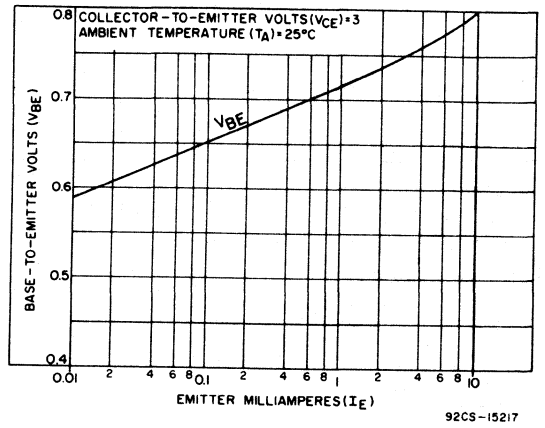


Fig.5 - V_{BE} vs I_E

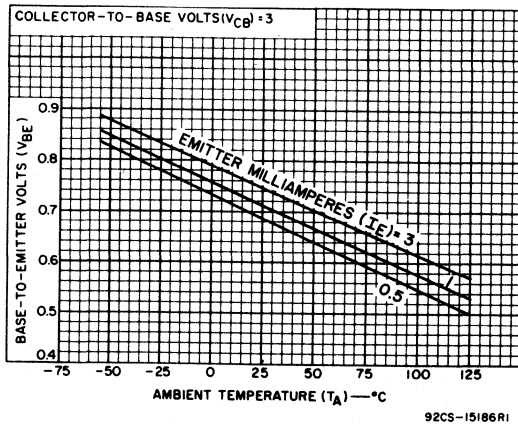
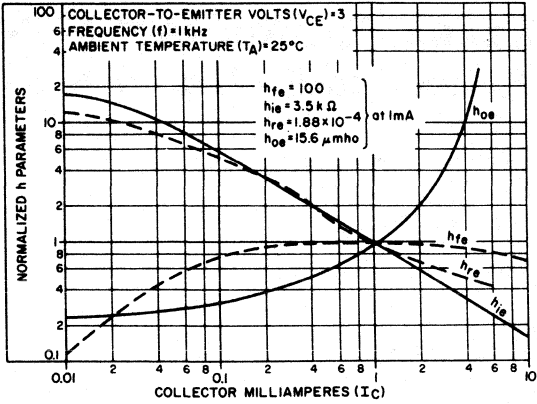
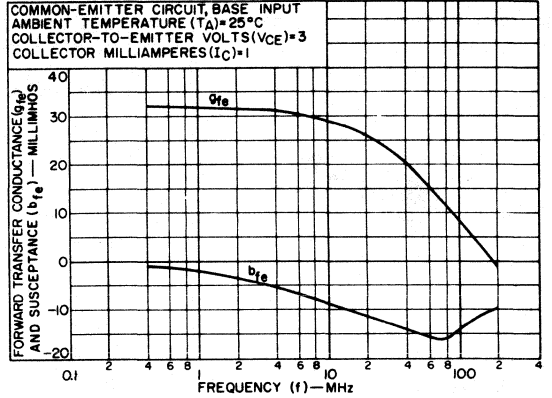


Fig.6 - V_{BE} vs T_A



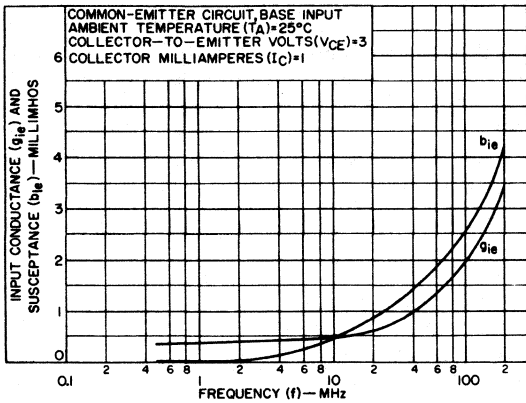
92CS-15190R2

Fig. 7 - Normalized h_{fe} , h_{ie} , h_{oe} , h_{re} vs I_C .



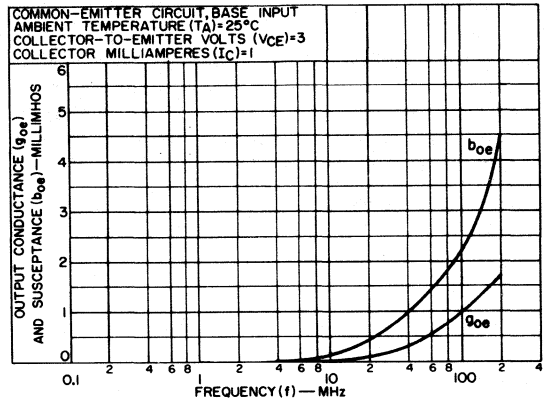
92CS-14257

Fig. 8 - y_{fe} vs f .



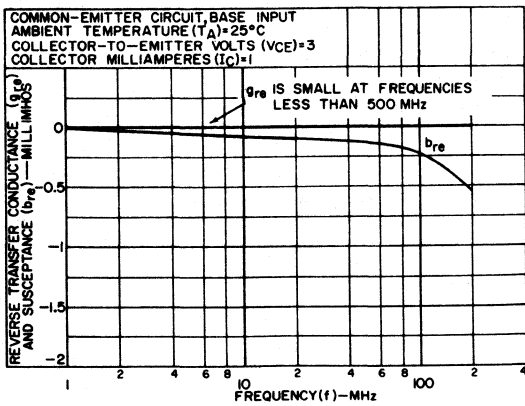
92CS-14259R1

Fig. 9 - y_{ie} vs f .



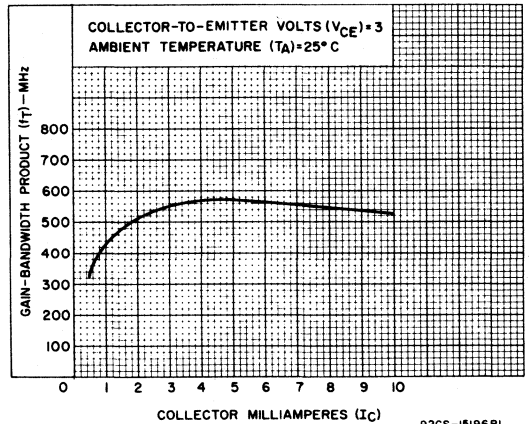
92CS-14260R1

Fig. 10 - y_{oe} vs f .



92CS-W258R1

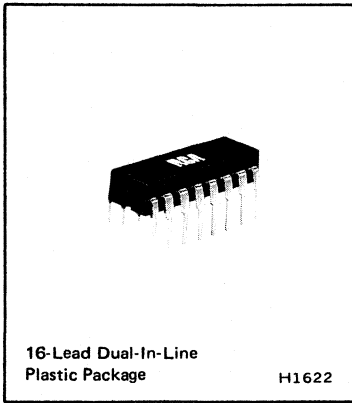
Fig. 11 - y_{re} vs f .



92CS-15196R1

Fig. 12 - f_T vs I_C .

CA3093E



General-Purpose High-Current N-P-N Transistor-Zener Diode - Diode Array

Applications

- Signal processing and switching systems operating from DC to VHF
- Lamp and relay driver
- Differential amplifier
- Temperature-compensated amplifier
- Thyristor firing
- Temperature-compensated shunt regulator
- Temperature-compensated series regulator
- Level shifting
- Voltage-level clamping

RCA CA3093E* is a versatile array of three high-current (to 100mA) NPN transistors, two 10%-tolerance Zener diodes and one conventional diode, all on a common monolithic substrate. Two of the transistors (Q_1 and Q_2) are matched at 1 mA for applications in which offset parameters are of special importance. The combination of positive Zener voltage temperature coefficients and negative forward base-emitter voltage temperature coefficients provides a unique temperature compensation capability.

Independent connections for each transistor and diode plus a separate terminal for the substrate permit maximum flexibility in circuit design.

- Current regulator
- Voltage clamping
- Simple off-line regulated supply
- See RCA Application Note, ICAN-5296 "Application of the RCA-CA3018 Circuit Transistor Array" for applications in addition to those given on pages 5 & 6 of this bulletin.

Features:

- 6 independent devices plus separate substrate connection
- Compensating temperature coefficients - V_{BE} and V_{D1} vs. V_Z

Transistors

- High I_C (100mA max)
- Matched pair (Q_1 & Q_2)
 - $V_{IO} = \pm 5mV$ max
 - $I_{IO} = 2.5 \mu A$ max
 at $I_C = 1mA$
- $\Delta V_{IO}/\Delta T = 5 \mu V/^\circ C$ typ

- $h_{FE} = 40$ min @ $I_C = 10mA$ or 50mA
- Low $V_{CEsat} \dots 0.7V$ max @ 50mA

Zener Diodes

- Two 1/4W Zeners
- $V_Z = 7V \pm 10\%$
- $z_Z = 15\Omega$ typ

Diode

- Close forward voltage match to V_{BE} 's of Q_1 and Q_2
- $V_{PIV} = 5.5V$ min.

*Formerly developmental type TA6119

Z_1 , Z_2 and D_1 are transistors internally connected as shown below.

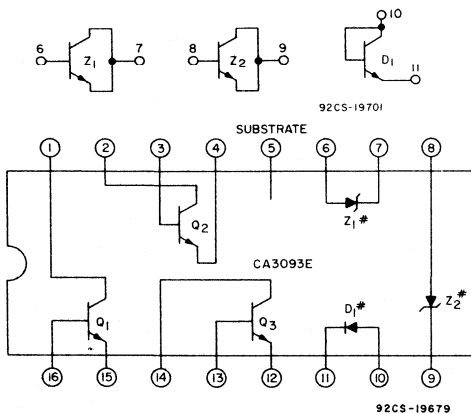


Fig. 1 - Functional diagram of the CA3093E (bottom view)

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

Power Dissipation:

Any one transistor	500	mW
Any one Zener Diode	250	mW
Total package	750	mW
Above 25°C	6.67	mW/ $^\circ\text{C}$
Derate linearly		
Ambient Temperature Range:		
Operating	-40 to +85	$^\circ\text{C}$
Storage	-55 to +150	$^\circ\text{C}$

The following maximum ratings apply for each transistor

Collector-to-Emitter Voltage (V_{CEO})	15	V
Collector-to-Base Voltage (V_{CBO})	20	V
Collector-to-Substrate Voltage (V_{C1O})*	20	V
Emitter-to-Base Voltage (V_{EBO})	5.5	V
Collector Current (I_{C})	100	mA
Base Current (I_{B})	35	mA

The following maximum ratings apply for each Zener Diode or Diode

Zener Diode dc Current (I_{Z})	35	mA
Zener Diode-to-Substrate Voltage (V_{Z1O})*	20	V
Diode (D1) Forward Current (I_{DF})	50	mA
Diode (D1) Reverse Voltage (V_{DR})	5.5	V
Diode (D1)-to-Substrate Voltage (V_{D1O})*	20	V

*The collector of each transistor, the cathode of each Zener diode, and the anode of the diode are isolated from the substrate by an internal diode. The substrate must be connected to a voltage which is more negative than any of these isolated terminals in order to

maintain isolation between devices and provide normal transistor action. To avoid undesired coupling between devices, the substrate terminal (5) should be maintained at either dc or signal (ac) ground. A suitable bypass capacitor can be used to establish a signal ground.

Linear Integrated Circuits

CA3093E

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$
For Equipment Design

CHARACTERISTICS	SYMBOL	TEST CONDITIONS		LIMITS			UNITS	
			Typ. Char. Curve Fig. No.	Min.	Typ.	Max.		
For Each Transistor:								
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 100\mu\text{A}, I_E = 0$	—	20	60	—	V	
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 1\text{mA}, I_B = 0$	—	15	24	—	V	
Collector-to-Substrate Breakdown Voltage	$V_{(BR)CIO}$	$I_{C1} = 100\mu\text{A}, I_B = 0, I_E = 0$	—	20	60	—	V	
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 500\mu\text{A}, I_C = 0$	—	5.5	6.9	—	V	
Collector-Cutoff Current	I_{CEO}	$V_{CE} = 10\text{V}, I_B = 0$	—	—	—	10	μA	
Collector-Cutoff Current	I_{CBO}	$V_{CB} = 10\text{V}, I_E = 0$	—	—	—	1	μA	
DC Forward Current Transfer Ratio	h_{FE}	$V_{CE} = 3\text{V}$	$I_C = 10\text{mA}$	2	40	76	—	
			$I_C = 50\text{mA}$		40	75	—	
Forward Base-to-Emitter Voltage	V_{BE}	$V_{CE} = 3\text{V}, I_C = 10\text{mA}$	3	0.65	0.74	0.85	V	
Collector-to-Emitter Saturation Voltage	V_{CEsat}	$I_C = 50\text{mA}, I_B = 5\text{mA}$	4	—	0.40	0.70	V	
Forward Base-to-Emitter Temp. Coefficient	$\Delta V_{BE}/\Delta T$	$I_E = 10\text{mA}$		—	-1.9	—	$\text{mV}/^\circ\text{C}$	
For Transistors Q1 and Q2 (As a Differential Amplifier):								
Absolute Input Offset Voltage	$ V_{IO} $	$V_{CE} = 3\text{V}, I_C = 1\text{mA}$	7	—	1.2	5	mV	
Absolute Input Offset Current	$ I_{IO} $		8	—	0.7	2.5	μA	
Temp. Coefficient of Offset Voltage	$ \Delta V_{IO}/\Delta T $	—	—	—	5	—	$\mu\text{V}/^\circ\text{C}$	
For Each Zener Diode								
Zener Voltage	V_Z	$I_Z = 10\text{mA}$	9	6.3	7	7.7	V	
Zener Impedance	Z_Z	$I_Z = 10\text{mA}, f = 1\text{kHz}$	10	—	15	25	Ω	
Zener Reverse Current	I_{ZR}	$V_Z = +5\text{V}$	—	—	—	1	μA	
Zener Voltage Temp. Coefficient	$\Delta V_Z/\Delta T$	$I_Z = 10\text{mA}$	9	— i.e.	+3.6 +0.5	—	$\text{mV}/^\circ\text{C}$ $\%/^\circ\text{C}$	
Zener-to-Substrate Breakdown Voltage	$V_{(BR)ZIO}$	$I_Z = 100\mu\text{A}$ (Terminals 7 & 9)	—	20	60	—	V	
Dissipation		Refer to Example in Application "a"		—	—	250	mW	
For Diode (D1)								
Diode Forward Voltage	V_{DF}	$I_C = 10\text{mA}, V_{CE} = 3\text{V}$	3	0.65	0.74	0.85	V	
Diode Forward Current	I_{DF}		—	—	—	50	mA	
Diode Reverse-Breakdown Voltage	$V_{(BR)DR}$	$I_{DR} = 500\mu\text{A}$	—	5.5	6.9	—	V	
Diode-to-Substrate Breakdown Voltage	$V_{(BR)DIO}$	$I_{Diode} = 100\mu\text{A}$ (Terminal 10)	—	20	60	—	V	
Diode Forward-Voltage Temp. Coefficient	$\Delta V_{DF}/\Delta T$	$I_{DF} = 5\text{mA}$	3	—	-1.9	—	$\text{mV}/^\circ\text{C}$	

TYPICAL STATIC CHARACTERISTICS

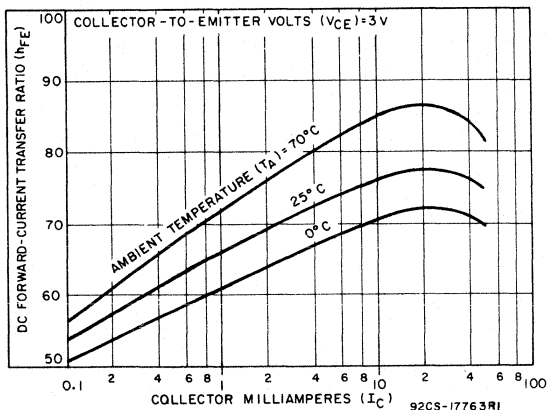


Fig. 2 - h_{FE} vs I_C

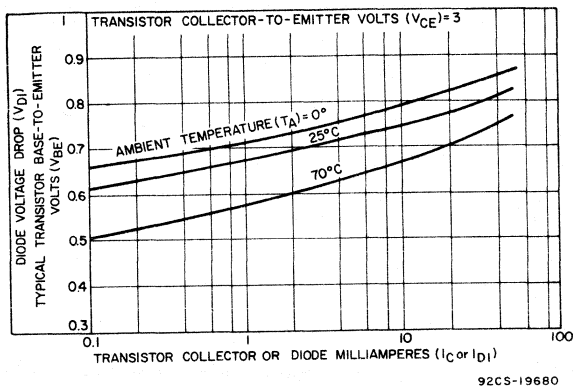


Fig. 3 - V_{BE} vs I_C and V_{D1} vs I_{D1}

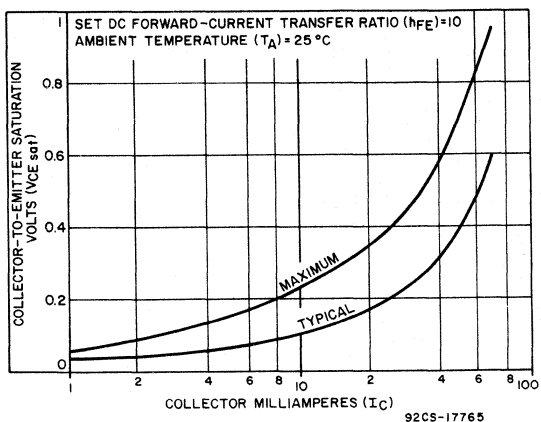


Fig. 4 - V_{CEsat} vs I_C at 25°C

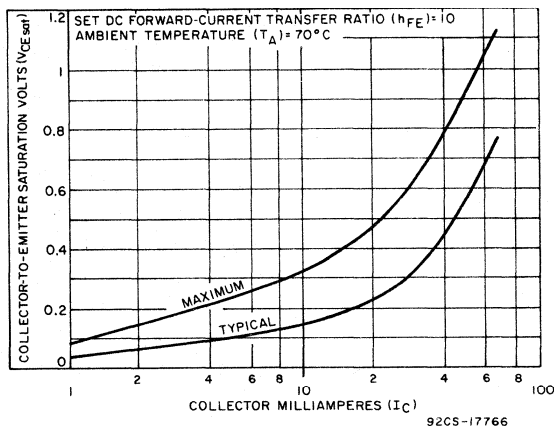


Fig. 5 - V_{CEsat} vs I_C at 70°C

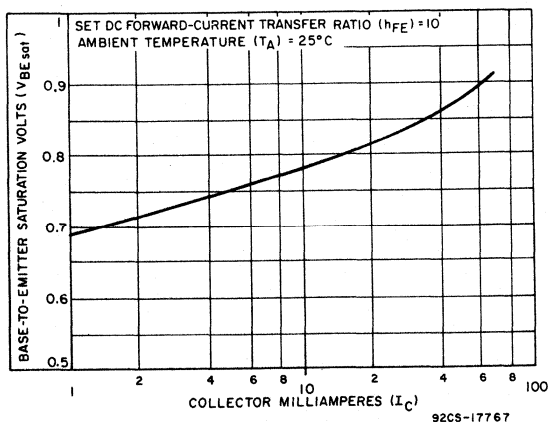


Fig. 6 - V_{BEsat} vs I_C

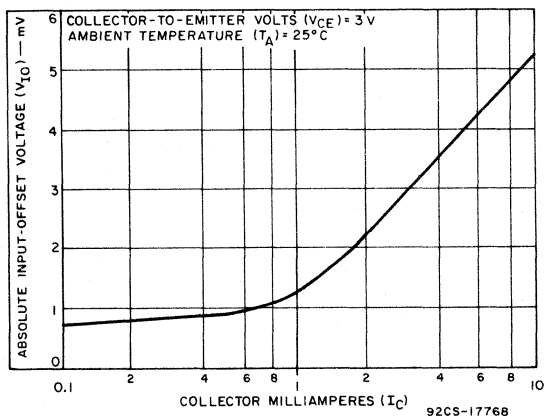


Fig. 7 - V_{IO} vs I_C (transistors Q1 and Q2 as a differential amplifier)

Linear Integrated Circuits

CA3093E

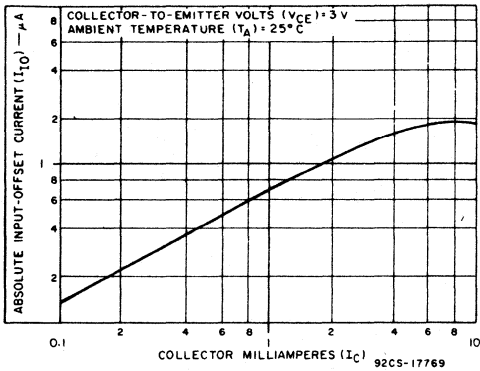


Fig. 8 — I_{IO} vs I_C (transistors Q1 and Q2 as a differential amplifier)

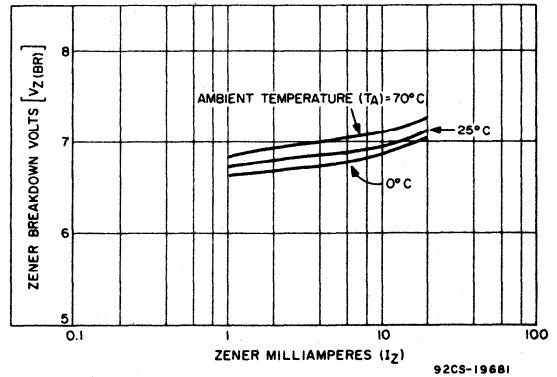


Fig. 9 — Typical Zener breakdown voltage vs current

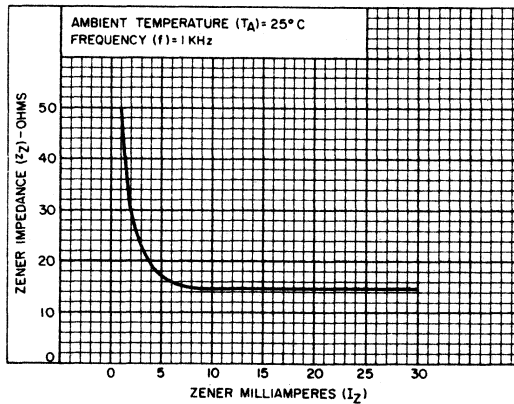
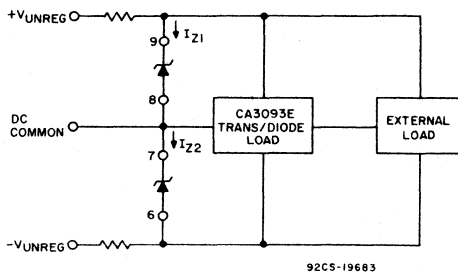


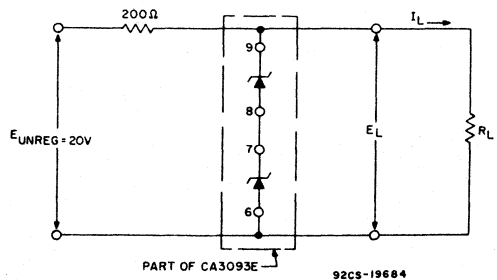
Fig. 10 — Typical Zener impedance vs current

TYPICAL APPLICATIONS

a) $\pm 7V$ Regulator supplying CA3093E Transistors plus an external load.



b) 14V Regulator for Q1, Q2, Q3



Sample Computation for Determining Permissible Zener Dissipation at $+25^\circ\text{C}$.

CA3093E Ratings at $T_A = +25^\circ\text{C}$
 Total Diss. Max = 750 mW (Derate @ 6.67 mW/ $^\circ\text{C}$ above 25°C)
 Each Zener Diss. Max = 250 mW
 Max. Zener Current = 35 mA

Assume CA3093E Transistor/Diode Load Dissipation = 350 mW then max. total Zener Diss. ($P_{Z1} + P_{Z2}$) = 750 - 350 = 400 mW

$$(I_{Z1} + I_{Z2})_{\text{max}} = \frac{400 \text{ mW}}{7V} = 57 \text{ mA}$$

(Note: Max. current rating on each Zener is 35 mA)

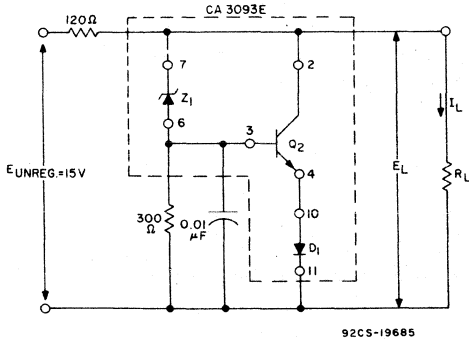
Typical Load Regulation
 for $I_L = 0$ to 25 mA
 $\Delta E_L / E_L \times 100 \approx -6\%$
 (no load to full load)

Typical Line Regulation
 $\frac{(\Delta E_L / E_L) \times 100}{\Delta E_{\text{unreg.}}} \approx \pm 0.9\%/V$

Typical Temperature Characteristic

$$\frac{\Delta E_L / E_L}{\Delta T} \times 100 = +0.05\%/^\circ\text{C}$$

c) 8.6V Temp.-Compensated Shunt Regulator



Typical Temperature Characteristic @ $R_L = 330\Omega$

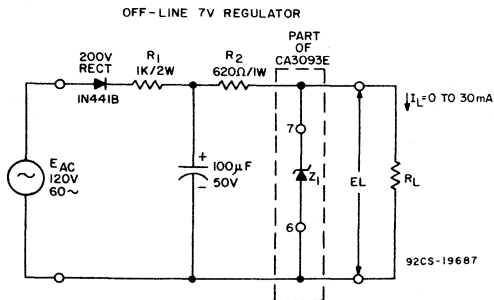
$$\frac{\Delta E_L / E_L}{\Delta T} \times 100 = \pm 0.007\%/^{\circ}\text{C}$$

Typical Load Regulation @ $I_L = 0$ to 40 mA
 $(\Delta E_L / E_L) \times 100 = -3\%$ (no load to full load)

Typical Line Regulation at $R_L = 330\Omega$

$$\frac{\Delta E_L / E_L}{\Delta E_{\text{unreg.}}} \times 100 = \pm 0.55\%/V$$

e) Off-Line 7V Regulator

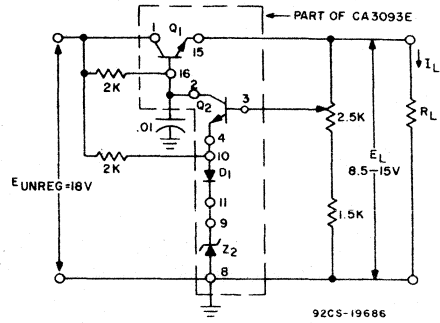


Typical E_L Ripple Voltage = 70 mV_{p-p}

Typical Load Regulation = $-\frac{\Delta E_L}{E_L} \times 100 = -8.5\%$ (no load to full load)
 $I_L = 0$ to 30 mA

Typical Line Regulation = $\frac{(\Delta E_L / E_L) \times 100}{\Delta E_{AC}} = \pm 0.075\%/V$

d) Temp.-Compensated Series Voltage Regulator



Typical Temperature Characteristic @ $E_L = 12V$

$$\frac{\Delta E_L / E_L}{\Delta T} \times 100 = \pm 0.009\%/^{\circ}\text{C}$$

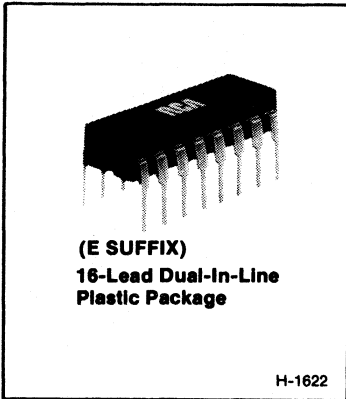
Typical Load Regulation @ $E_L = 12V$
 $I_L = 0$ to 40 mA

$$\frac{\Delta E_L}{E_L} \times 100 = \pm 0.4\%$$
 (no load to full load)

Typical Line Regulation @ $E_L = 12V$

$$\frac{(\Delta E_L / E_L) \times 100}{\Delta E_{\text{unreg.}}} = \pm 0.45\%/V$$

CA3096, CA3096A, CA3096C



N-P-N/P-N-P Transistor Array

Five-Independent Transistors: Three n-p-n and Two p-n-p

Applications:

- Differential Amplifiers
- DC Amplifiers
- Sense Amplifiers
- Level Shifters
- Timers
- Lamp and Relay Drivers
- Thyristor Firing Circuits
- Temperature-Compensated Amplifiers
- Operational Amplifiers

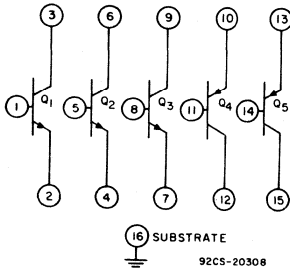
RCA-CA3096CE, CA3096E, and CA3096AE are general-purpose high-voltage silicon transistor arrays. Each array consists of five independent transistors (two p-n-p and three n-p-n types) on a common substrate, which has a separate connection. Independent connections for each transistor permit maximum flexibility in circuit design.

Types CA3096AE, CA3096E, and CA3096CE are identical, except that the CA3096AE specifications include parameter matching and greater stringency in I_{CBO} , I_{CEO} , and $V_{CE(SAT)}$. The CA3096CE is a relaxed version of the CA3096E.

The CA3096CE, CA3096E, and CA3096AE are supplied in 16-lead dual-in-line plastic packages. (E-suffix). The CA3096 is also available in chip form. (H suffix).

CA3096AE, CA3096E, CA3096CE
ESSENTIAL DIFFERENCES

CHARACTERISTIC	CA3096AE	CA3096E	CA3096CE
$V_{(BR)CEO}$ (V)	n-p-n	35	35
	Min. p-n-p	-40	-40
$V_{(BR)CBO}$ (V)	n-p-n	45	45
	Min. p-n-p	-40	-40
h_{FE} @ 1 mA	n-p-n	150-500	150-500
	p-n-p	20-150	20-150
h_{FE} @ 100 μ A	n-p-n	40-200	40-200
	p-n-p	20-150	15-200
I_{CBO} (nA)	n-p-n	40	100
	Max. p-n-p	-40	-100
I_{CEO} (nA)	n-p-n	100	1000
	Max. p-n-p	-100	-1000
$V_{CE(SAT)}$ (V)	n-p-n	0.5	0.7
	Max. p-n-p	0.5	0.7
$ V_{IQ} $ (mV)	n-p-n	5	-
	Max. p-n-p	5	-
$ I_{IQ} $ (μ A)	n-p-n	0.6	-
	Max. p-n-p	0.25	-



Schematic Diagram

CA3096, CA3096A, CA3096C

MAXIMUM RATINGS, Absolute-Maximum Values:

	EACH N-P-N	EACH P-N-P	
COLLECTOR-TO-EMITTER VOLTAGE, V_{CEO} :			
CA3096AE, CA3096E	35	-40	V
CA3096CE	24	-24	V
COLLECTOR-TO-BASE VOLTAGE, V_{CBO} :			
CA3096AE, CA3096E	45	-40	V
CA3096CE	30	-24	V
COLLECTOR-TO-SUBSTRATE VOLTAGE, V_{C1O} :			
CA3096AE, CA3096E	45	-	V
CA3096CE	30	-	V
EMITTER-TO-SUBSTRATE VOLTAGE, V_{E1O} :			
CA3096AE, CA3096E	-	-40	V
CA3096CE	-	-24	V
EMITTER-TO-BASE VOLTAGE, V_{EBO} :			
CA3096E, CA3096E	6	-40	V
CA3096CE	6	-24	V
COLLECTOR CURRENT, I_C (All Types)	50	-10	mA
POWER DISSIPATION, P_D :			
Up to $T_A = 55^\circ\text{C}$:			
Device (Total)		750	mW
Each Transistor		200	mW
Above $T_A = 55^\circ\text{C}$ derate linearly at		6.67	mW/ $^\circ\text{C}$
AMBIENT-TEMPERATURE RANGE, T_A :			
Operating			-55 to +125 $^\circ\text{C}$
Storage			-65 to +150 $^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):			
At distance 1/16 ± 1/32 inch (1.59 ± 0.79 mm)			
from case for 10 s max.			265 $^\circ\text{C}$

STATIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$
For Equipment Design

CHARACTERISTIC	TEST CONDITIONS	LIMITS									UNITS
		CA3096AE			CA3096E			CA3096CE			
		Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
For Each n-p-n Transistor											
I_{CBO}	$V_{CB} = 10\text{ V}, I_E = 0$	-	0.001	40	-	0.001	100	-	0.001	100	nA
I_{CEO}	$V_{CE} = 10\text{ V}, I_B = 0$	-	0.006	100	-	0.006	1000	-	0.006	1000	nA
$V_{(BR)CEO}$	$I_C = 1\text{ mA}, I_B = 0$	35	50	-	35	50	-	24	35	-	V
$V_{(BR)CBO}$	$I_C = 10\ \mu\text{A}, I_E = 0$	45	100	-	45	100	-	30	80	-	V
$V_{(BR)C1O}$	$I_{C1} = 10\ \mu\text{A}, I_B = I_E = 0$	45	100	-	45	100	-	30	80	-	V
$V_{(BR)EBO}$	$I_E = 10\ \mu\text{A}, I_C = 0$	6	8	-	6	8	-	6	8	-	V
V_Z	$I_Z = 10\ \mu\text{A}$	6	7.9	9.8	6	7.9	9.8	6	7.9	9.8	V
$V_{CE(SAT)}$	$I_C = 10\text{ mA}, I_B = 1\text{ mA}$	-	0.24	0.5	-	0.24	0.7	-	0.24	0.7	V
V_{BE}	$I_C = 1\text{ mA}$	0.6	0.69	0.78	0.6	0.69	0.78	0.6	0.69	0.78	V
h_{FE}	$V_{CE} = 5\text{ V}$	150	390	500	150	390	500	100	390	670	
$ \Delta V_{BE}/\Delta T $	$I_C = 1\text{ mA}, V_{CE} = 5\text{ V}$	-	1.9	-	-	1.9	-	-	1.9	-	mV/ $^\circ\text{C}$

Linear Integrated Circuits

CA3096, CA3096A, CA3096C

STATIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$ (Cont'd)
For Equipment Design

CHARACTERISTIC	TEST CONDITIONS	LIMITS									UNITS
		CA3096AE			CA3096E			CA3096CE			
		Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
For Each p-n-p Transistor											
I_{CBO}	$V_{CB} = -10\text{V}$, $I_E = 0$	-	-0.006	-40	-	-0.06	-100	-	-0.06	-100	nA
I_{CEO}	$V_{CE} = -10\text{V}$, $I_B = 0$	-	-0.12	-100	-	-0.12	-1000	-	-0.12	-1000	nA
$V_{(BR)CEO}$	$I_C = -100\mu\text{A}$, $I_B = 0$	-40	-75	-	-40	-75	-	-24	-30	-	V
$V_{(BR)CBO}$	$I_C = -10\mu\text{A}$, $I_E = 0$	-40	-80	-	-40	-80	-	-24	-60	-	V
$V_{(BR)EBO}$	$I_E = -10\mu\text{A}$, $I_C = 0$	-40	-100	-	-40	-100	-	-24	-80	-	V
$V_{(BR)EIO}$	$I_{EI} = 10\mu\text{A}$, $I_B = I_C = 0$	-40	-100	-	-40	-100	-	-24	-80	-	V
$V_{CE(SAT)}$	$I_C = -1\text{mA}$, $I_B = -100\mu\text{A}$	-	-0.16	-0.4	-	-0.16	-0.4	-	-0.16	-0.4	V
V_{BE}	$I_C = -100\mu\text{A}$, $V_{CE} = -5\text{V}$	-0.5	-0.6	-0.7	-0.5	-0.6	-0.7	-0.5	-0.6	-0.7	V
h_{FE}	$I_C = -100\mu\text{A}$, $V_{CE} = -5\text{V}$	40	85	250	40	85	250	30	85	300	
	$I_C = -1\text{mA}$, $V_{CE} = -5\text{V}$	20	47	200	20	47	200	15	47	200	
$ \Delta V_{BE}/\Delta T $	$I_C = -100\mu\text{A}$, $V_{CE} = -5\text{V}$	-	2.2	-	-	2.2	-	-	2.2	-	mV/ $^\circ\text{C}$

I_{CBO} Collector-Cutoff Current
 I_{CEO} Collector-Cutoff Current
 $V_{(BR)CEO}$ Collector-to-Emitter Breakdown Voltage
 $V_{(BR)CBO}$ Collector-to-Base Breakdown Voltage
 $V_{(BR)CIO}$ Collector-to-Substrate Breakdown Voltage
 $V_{(BR)EBO}$ Emitter-to-Base Breakdown Voltage

V_Z Emitter-to-Base Zener Voltage
 $V_{CE(SAT)}$ Collector-to-Emitter Saturation Voltage
 V_{BE} Base-to-Emitter Voltage
 h_{FE} DC Forward-Current Transfer Ratio
 $|\Delta V_{BE}/\Delta T|$ Magnitude of Temperature Coefficient: (for each transistor)

CA3096, CA3096A, CA3096C

STATIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$ (CA3096AE Only)
For Equipment Design

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		CA3096AE			
		Min.	Typ.	Max.	
For Transistors Q1 and Q2 (as a Differential Amplifier)					
Absolute Input Offset Voltage, $ V_{IO} $	$V_{CE} = 5\text{ V}, I_C = 1\text{ mA}$	-	0.3	5	mV
Absolute Input Offset Current, $ I_{IO} $		-	0.07	0.6	μA
Absolute Input Offset Voltage Temperature Coefficient, $\frac{ \Delta V_{IO} }{\Delta T}$		-	1.1	-	$\mu\text{V}/^\circ\text{C}$
For Transistors Q4 and Q5 (As a Differential Amplifier)					
Absolute Input Offset Voltage, $ V_{IO} $	$V_{CE} = -5\text{ V}, I_C = -100\mu\text{A}$ $R_S = 0$	-	0.15	5	mV
Absolute Input Offset Current, $ I_{IO} $		-	2	250	nA
Absolute Input Offset Voltage Temperature Coefficient, $\frac{ \Delta V_{IO} }{\Delta T}$		-	0.54	-	$\mu\text{V}/^\circ\text{C}$

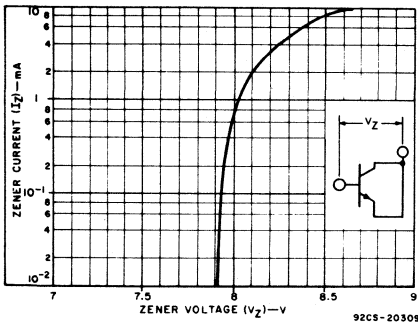


Fig. 1 - Base-to-emitter zener characteristic (n-p-n).

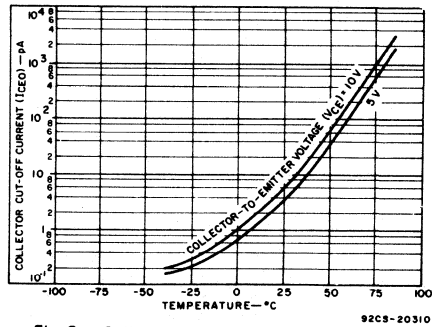


Fig. 2 - Collector cut-off current (I_{CEO}) as a function of temperature (n-p-n).

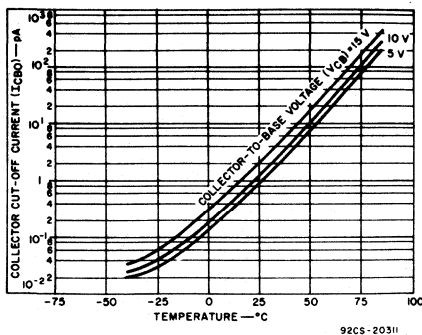


Fig. 3 - Collector cut-off current (I_{CBO}) as a function of temperature (n-p-n).

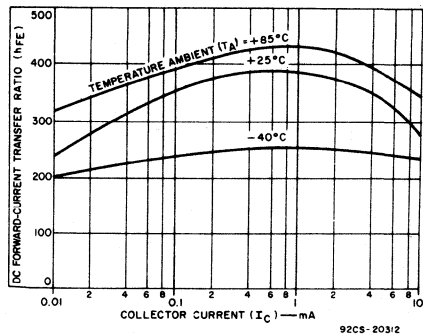


Fig. 4 - Transistor (n-p-n) h_{FE} as a function of collector current.

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DYNAMIC

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

Typical Values Intended Only for Design Guidance

CHARACTERISTICS	TEST CONDITIONS	TYPICAL VALUES	UNITS
For Each n-p-n Transistor			
Noise Figure (low frequency), NF	$f = 1\text{ kHz}, V_{CE} = 5\text{ V}, I_C = 1\text{ mA}, R_S = 1\text{ k}\Omega$	2.2	dB
Low-Frequency, Input Resistance, R_i	$f = 1.0\text{ kHz}, V_{CE} = 5\text{ V}, I_C = 1\text{ mA}$	10	$\text{k}\Omega$
Low-Frequency Output Resistance, R_o		80	$\text{k}\Omega$
Admittance Characteristics:			
Forward Transfer Admittance, $\frac{g_{fe}}{y_{fe} b_{fe}}$	$f = 1\text{ MHz}, V_{CE} = 5\text{ V}, I_C = 1\text{ mA}$	7.5	mmho
		-j13	
Input Admittance, $\frac{g_{ie}}{y_{ie} b_{ie}}$		2.2	mmho
	j3.1		
Output Admittance, $\frac{g_{oe}}{y_{oe} b_{oe}}$		0.76	mmho
		j2.4	
Gain-Bandwidth Product, f_T	$V_{CE} = 5\text{ V}, I_C = 1.0\text{ mA}$	280	MHz
	$V_{CE} = 5\text{ V}, I_C = 5\text{ mA}$	335	
Emitter-to-Base Capacitance, C_{EB}	$V_{EB} = 3\text{ V}$	0.75	pF
Collector-to-Base Capacitance, C_{CB}	$V_{CB} = 3\text{ V}$	0.46	pF
Collector-to-Substrate Capacitance, C_{CI}	$V_{CI} = 3\text{ V}$	3.2	pF
For Each p-n-p Transistor			
Noise Figure (low frequency), NF	$f = 1\text{ kHz}, I_C = 100\text{ }\mu\text{A}, R_S = 1\text{ k}\Omega$	3	dB
Low-Frequency Input Resistance, R_i	$f = 1\text{ kHz}, V_{CE} = 5\text{ V}, I_C = 100\text{ }\mu\text{A}$	27	$\text{k}\Omega$
Low-Frequency Output Resistance, R_o		680	$\text{k}\Omega$
Gain-Bandwidth Product, f_T	$V_{CE} = 5\text{ V}, I_C = 100\text{ }\mu\text{A}$	6.8	MHz
Emitter-to-Base Capacitance, C_{EB}	$V_{EB} = -3\text{ V}$	0.85	pF
Collector-to-Base Capacitance, C_{CB}	$V_{CB} = -3\text{ V}$	2.25	pF
Base-to-Substrate Capacitance, C_{BI}	$V_{BI} = 3\text{ V}$	3.05	pF

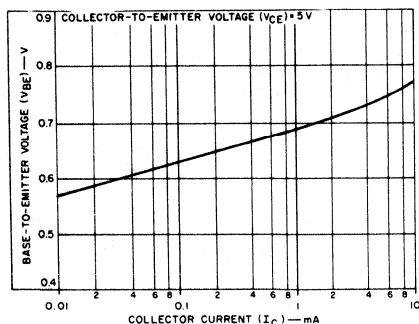


Fig. 5 - V_{BE} (n-p-n) as a function of collector current.

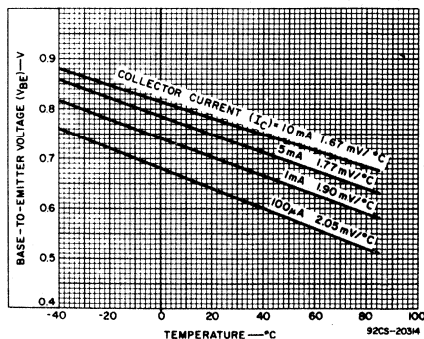


Fig. 6 - V_{BE} (n-p-n) as a function of temperature.

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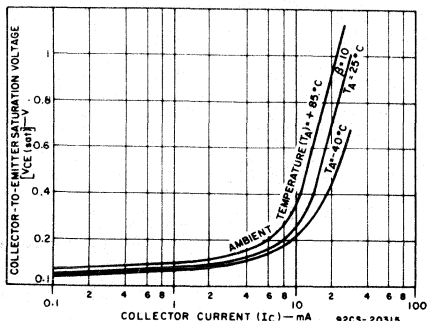


Fig. 7 - $V_{CE(SAT)}$ (n-p-n) as a function of collector current.

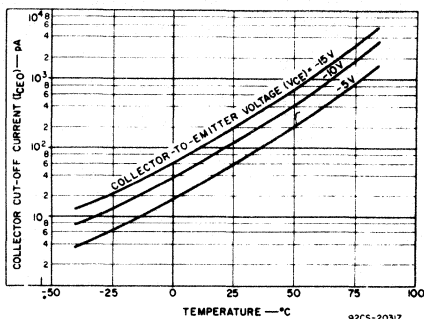


Fig. 8 - Collector cut-off current (I_{CEO}) as a function of temperature (p-n-p).

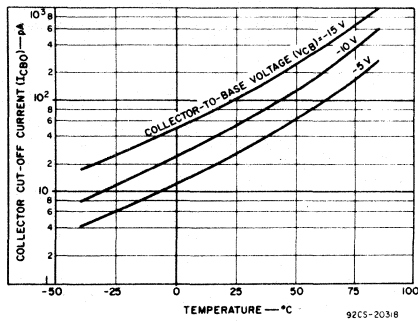


Fig. 9 - Collector cut-off current (I_{CBO}) as a function of temperature (p-n-p).

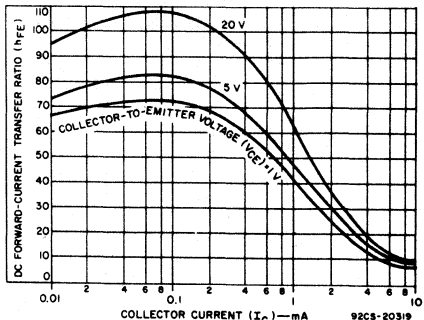


Fig. 10 - Transistor (p-n-p) h_{FE} as a function of collector current.

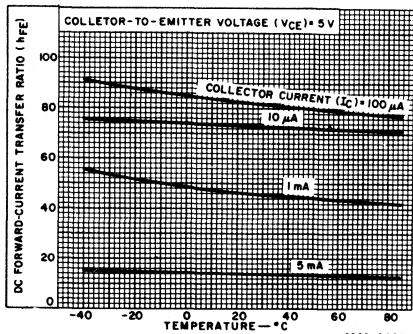


Fig. 11 - Transistor (p-n-p) h_{FE} as a function of temperature.

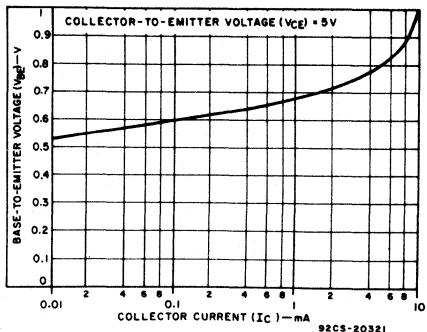


Fig. 12 - V_{BE} (p-n-p) as a function of collector current.

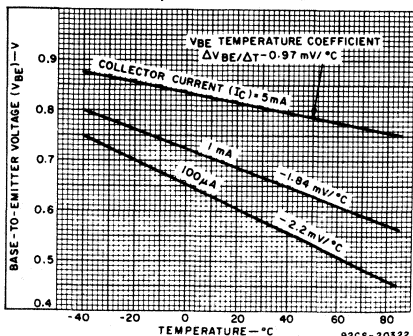


Fig. 13 - V_{BE} (p-n-p) as a function of temperature.

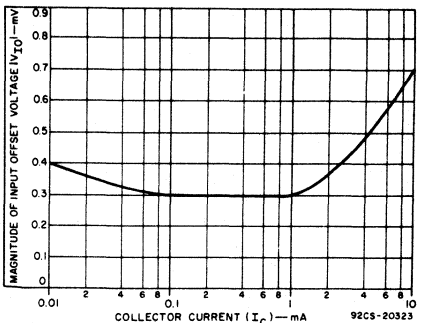


Fig. 14 - Magnitude of input offset voltage $|V_{IO}|$ as a function of collector current for n-p-n transistor Q_1-Q_2 .

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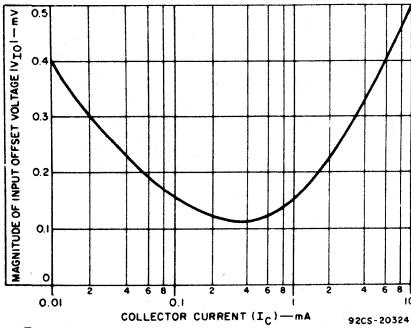


Fig. 15 - Magnitude of input offset voltage $|V_{IO}|$ as a function of collector current for p-n-p transistor Q_4-Q_5

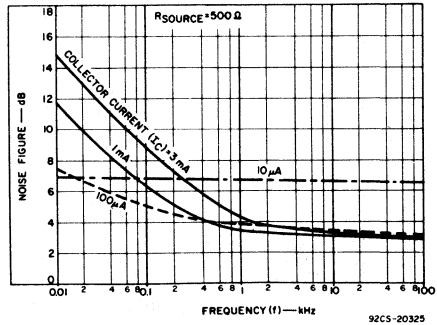


Fig. 16 - Noise figure as a function of frequency for n-p-n transistors.

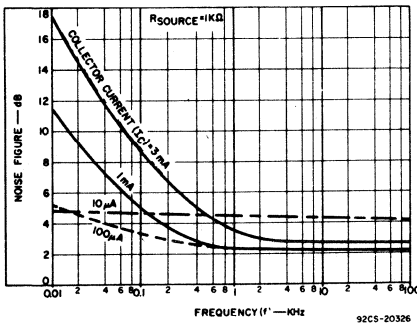


Fig. 17 - Noise figure as a function of frequency for n-p-n transistors.

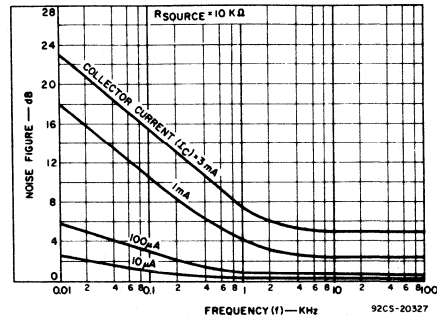


Fig. 18 - Noise as a function of frequency for n-p-n transistors.

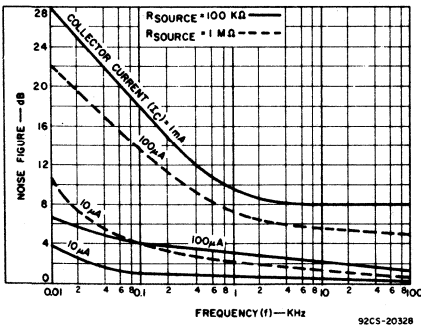


Fig. 19 - Noise figure as a function of frequency for n-p-n transistors.

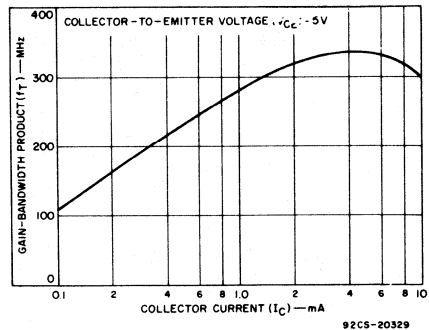


Fig. 20 - Gain-bandwidth product as a function of collector current (n-p-n).

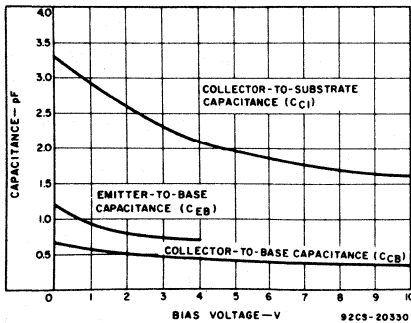


Fig. 21 - Capacitance as a function of bias voltage (n-p-n).

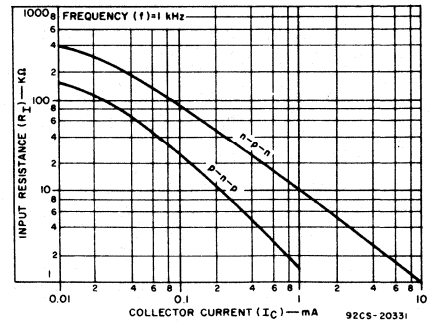


Fig. 22 - Input resistance as a function of collector current.

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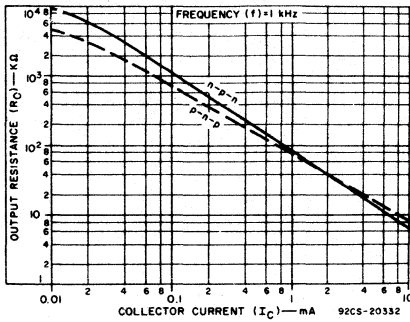


Fig. 23 - Output resistance as a function of collector current.

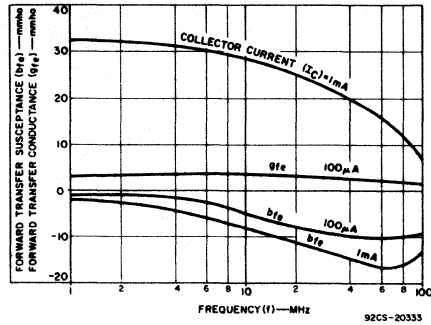


Fig. 24 - Forward transconductance as a function of frequency.

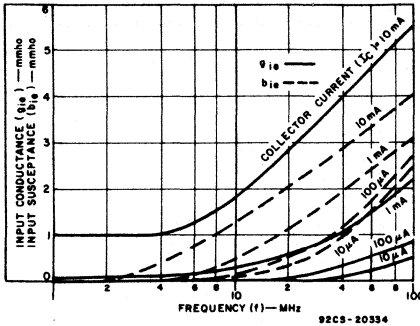


Fig. 25 - Input admittance as a function of frequency.

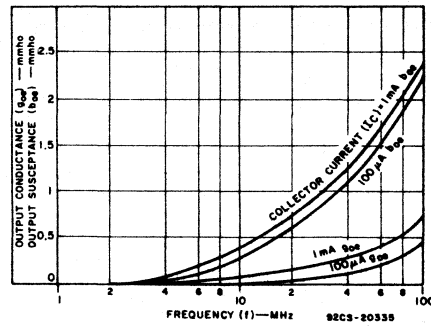


Fig. 26 - Output admittance as a function of frequency.

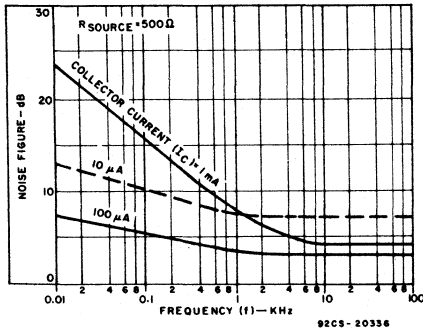


Fig. 27 - Noise figure as a function of frequency (p-n-p).

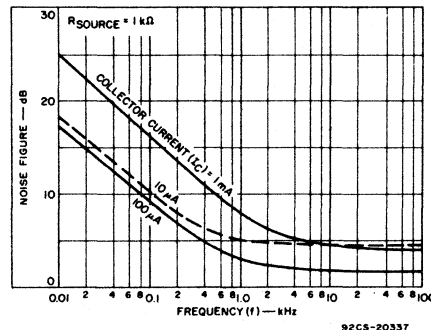


Fig. 28 - Noise figure as a function of frequency (p-n-p).

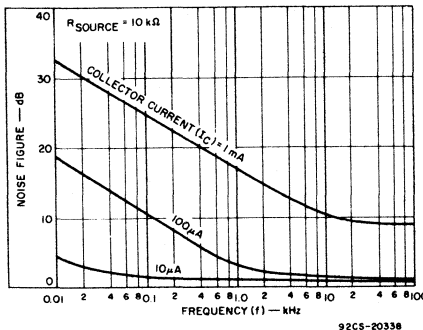


Fig. 29 - Noise figure as a function of frequency (p-n-p).

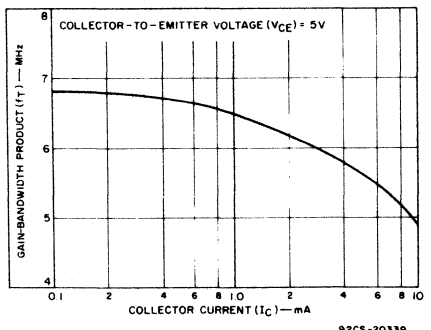


Fig. 30 - Gain-bandwidth product as a function of collector current (p-n-p).

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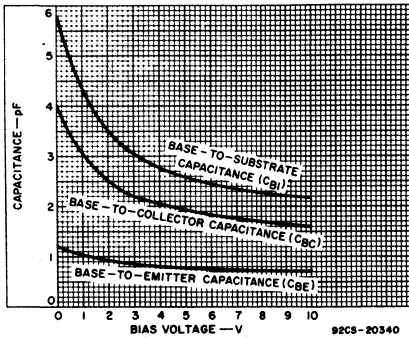


Fig. 31 - Capacitance as a function of bias voltage (p-n-p).

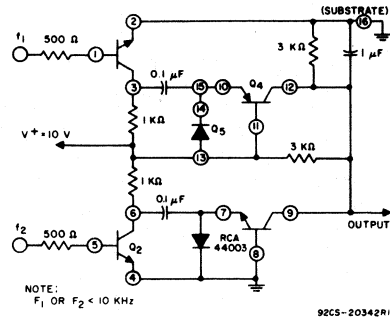


Fig. 32 - Frequency comparator using CA3096E.

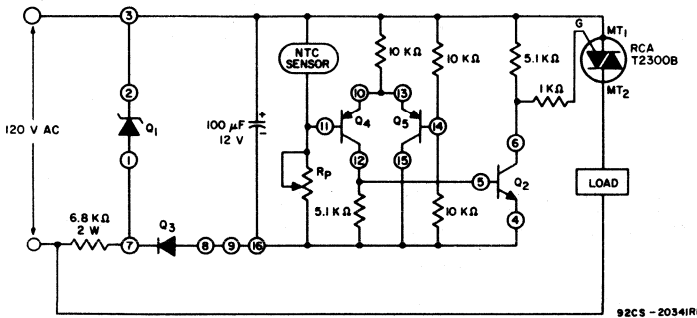


Fig. 33 - Line-operated level switch using CA3096AE or CA3096E.

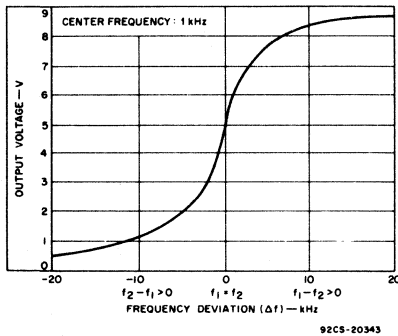


Fig. 34 - Frequency comparator characteristics.

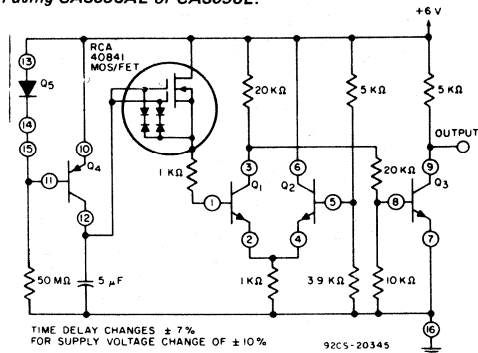


Fig. 35 - One-minute timer using CA3096AE and a MOS/FET.

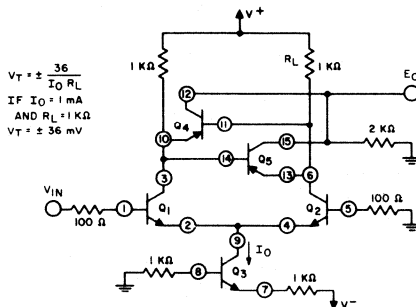
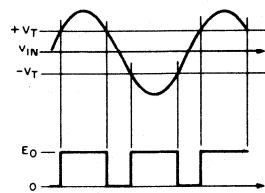


Fig. 36 - CA3096AE small-signal zero-voltage detector having noise immunity.



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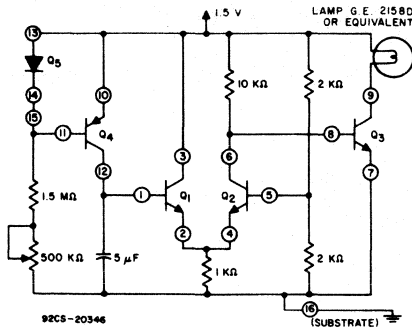


Fig. 37 - Ten-second timer operated from 1.5-volt supply using CA3096E.

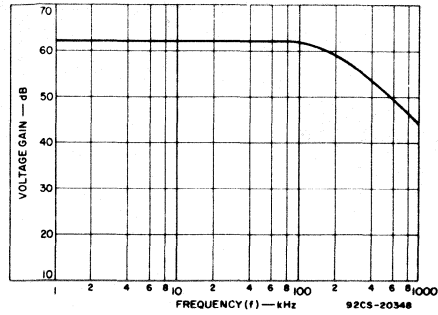


Fig. 38 - Gain-frequency characteristics.

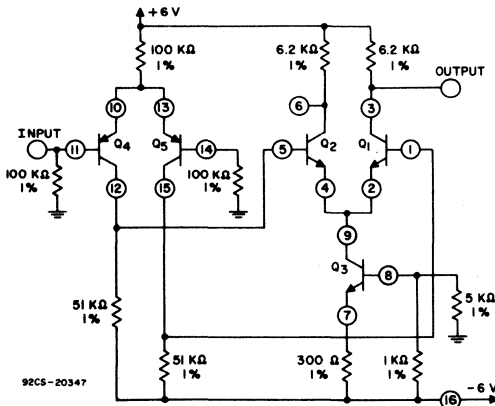
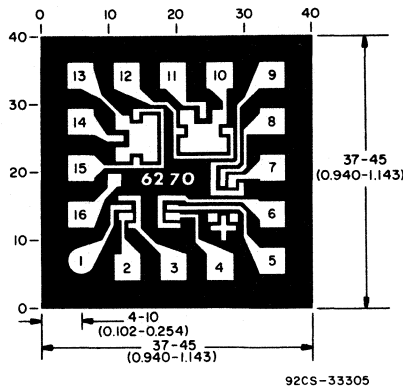


Fig. 39 - Cascade of differential amplifiers using CA3096AE.

Features:

1. Can be operated with either dual supply or single supply.
2. Wide-input common-mode range +5 V to -5 V.
3. Low bias current: <math>< 1 \mu A</math>.

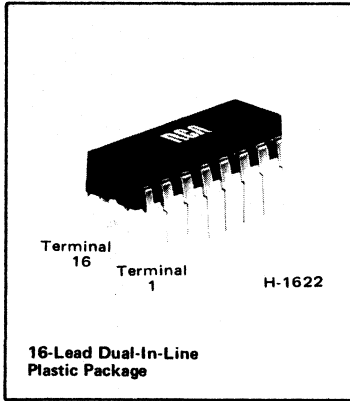


CA3096H

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

The photographs and dimensions represent a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

CA3097E



Thyristor/Transistor Array

For Military, Commercial, and Industrial Applications

Includes:

- Uncommitted n-p-n transistor
- Sensitive-gate silicon controlled rectifier
- Programmable unijunction transistor (PUT)
- p-n-p/n-p-n transistor pair
- Zener diode
- Separate substrate connection

Features:

- Complete isolation between elements
- n-p-n transistor - $V_{CE0} = 30\text{ V (min.)}$
 $I_C = 100\text{ mA (max.)}$
- p-n-p/n-p-n transistor pair - beta ≥ 8000 (typ.) @ $I_C = 10\text{ mA}$, individual p-n-p, n-p-n, or transistor pair operation
- Programmable unijunction transistor [PUT] - peak-point current = 15 nA (typ.) at $R_G = 1\text{ M}\Omega$; $V_{AK} = \pm 30\text{ V}$
- (PUT) Extremely long RC time constants with low value of external capacitor
- Sensitive-gate silicon controlled rectifier (SCR) - 150 mA forward current (max.)

- Zener-diode impedance (Z_Z) = 15Ω (typ.) at 10 mA

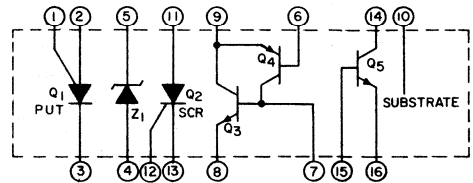
Applications:

- Timers
- Light dimmers/motor controls
- Oscillators
- "One-shot" multivibrators
- Voltage regulators
- Comparators, Schmitt triggers
- Constant-current sources
- Amplifiers
- Logic circuits
- SCR triggering
- Pulse circuits

RCA-CA3097E* Thyristor/Transistor Array is a monolithic integrated circuit that enables circuit designers to further integrate control systems. The CA3097E consists of five independent and completely isolated elements on one chip: an n-p-n transistor, a p-n-p/n-p-n transistor pair, a zener diode, a programmable unijunction transistor (PUT), and a sensitive-gate silicon controlled rectifier (SCR).

The CA3097 is supplied in either the 16-lead dual-in-line plastic package ("E" suffix) or the chip version ("H" suffix), and operates over the full military-temperature range of -55 to +125°C.

*Formerly Dev. No. TA6281.



92CS-21935

Fig. 1 — Schematic diagram of CA3097E.

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

Isolation Voltage, any terminal to substrate*	+50 V
Dissipation, Total Package:	
Up to $T_A = 55^\circ\text{C}$	750 mW
Above $T_A = 55^\circ\text{C}$	derate linearly at 6.67 mW/ $^\circ\text{C}$
Ambient Temperature Range:	
Operating	-55 to +125 $^\circ\text{C}$
Storage	-65 to +150 $^\circ\text{C}$
Lead Temperature (During Soldering):	
At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10 seconds max.	+265 $^\circ\text{C}$
Each n-p-n Transistor (Q3,Q5)	
The following ratings apply with terminals 6 & 9 connected together.	
Collector-to-Emitter Voltage (V_{CEO})	30 V
Collector-to-Base Voltage (V_{CBO})	50 V
Emitter-to-Base Voltage (V_{EBO})	5 V
Collector Current (I_C)	100 mA
Base Current (I_B)	20 mA
Dissipation (P_D)	500 mW
p-n-p Transistor (Q4)	
The following ratings apply with terminals 7 & 8 connected together.	
Collector-to-Emitter Voltage (V_{CEO})	-40 V
Collector-to-Base Voltage (V_{CBO})	-50 V
Emitter-to-Base Voltage (V_{EBO})	-40 V
Collector Current (I_C)	-10 mA
Base Current (I_B)	-3 mA
Dissipation (P_D)	200 mW
p-n-p/n-p-n Transistor Pair (Q3,Q4)	
Dissipation (P_D)	500 mW
Programmable Unijunction Transistor, PUT (Q1)	
Gate-to-Cathode Positive Voltage (V_{GK})	30 V
Gate-to-Cathode Negative Voltage (V_{GKR})	5 V
Gate-to-Anode Negative Voltage (V_{GA})	30 V
Anode-to-Cathode Voltage (V_{AK})	± 30 V
DC Anode Current	150 mA
Peak Anode Non-Recurrent Forward (On-State) Current (10 μs pulse)	2 A
Total Average Dissipation	300 mW
Silicon Controlled Rectifier, SCR (Q2)	
Repetitive Peak Reverse Voltage (V_{RRXM}), $R_{GK} = 1 \text{ K}\Omega$	30 V
Repetitive Peak Off-State Voltage (V_{DRXM}), $R_{GK} = 1 \text{ k}\Omega$	30 V
DC On-State Current (I_{TDC})	150 mA
Peak Surge (Non-Repetitive) On-State Current (10 μs pulse)	2 A
Forward Peak Gate Current (I_{GFM})	20 mA
Peak Gate-to-Cathode Reverse Voltage (V_{GRM})	5 V
Total Average Dissipation	300 mW
Zener Diode, (Z1)	
DC Current (I_Z)	25 mA
Dissipation (P_D)	250 mW

* One or more of the terminals of each element of the CA3097E is isolated from the substrate by a junction diode. In order to maintain electrical isolation between elements, the substrate terminal must be connected to a voltage which is no more positive than that of any other terminal. To avoid undesirable coupling between elements, the substrate terminal (terminal 10) should be maintained at either dc or signal (ac) ground.

Linear Integrated Circuits

CA3097E

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CONDITIONS Ambient Temperature (T _A) = 25°C Unless Otherwise Specified	FIG. NO.	LIMITS			UNITS
				Min.	Typ.	Max.	
n-p-n TRANSISTORS Q3, Q5 (TERMINALS 6 and 9 CONNECTED)							
COLLECTOR CUTOFF CURRENT	I _{CBO}	V _{CB} = 10 V, I _E = 0		–	–	1	μA
COLLECTOR CUTOFF CURRENT	I _{CEO}	V _{CE} = 10 V, I _B = 0		–	–	10	μA
COLLECTOR-TO-EMITTER BREAKDOWN VOLTAGE	V _{(BR)CEO}	I _C = 100μA, I _B = 0		30	–	–	V
COLLECTOR-TO-BASE BREAKDOWN VOLTAGE	V _{(BR)CBO}	I _C = 100μA, I _E = 0		50	–	–	V
COLLECTOR-TO-SUBSTRATE BREAKDOWN VOLTAGE	V _{(BR)CIO}	I _{C1} = 100μA, I _B = 0, I _E = 0		50	–	–	V
EMITTER-TO-BASE BREAKDOWN VOLTAGE	V _{(BR)EBO}	I _E = 100μA, I _C = 0		5	7.5	10	V
COLLECTOR-TO-EMITTER SATURATION VOLTAGE	V _{CE(SAT)}	I _C = 50mA, I _B = 5mA I _C = 10mA, I _B = 1 mA	5	–	–	0.65	V
BASE-TO-EMITTER SATURATION VOLTAGE	V _{BE(SAT)}	I _C = 10mA, I _B = 1mA	2	–	0.76	–	V
BASE-TO-EMITTER VOLTAGE	V _{BE}	V _{CE} = 3V, I _C = 10mA	3	0.65	0.73	0.85	V
DC FORWARD-CURRENT TRANSFER RATIO	h _{FE}	V _{CE} = 3V, I _C = 10mA V _{CE} = 3V, I _C = 50mA	4	100	130	–	
				80	120	–	
p-n-p TRANSISTOR Q4 (TERMINALS 7 and 8 CONNECTED)							
COLLECTOR CUTOFF CURRENT	I _{CBO}	V _{CB} = -10 V, I _E = 0		–	–	-1	μA
COLLECTOR CUTOFF CURRENT	I _{CEO}	V _{CE} = -10 V, I _B = 0		–	–	-10	μA
COLLECTOR-TO-EMITTER BREAKDOWN VOLTAGE	V _{(BR)CEO}	I _C = -100μA, I _B = 0		-40	–	–	V
COLLECTOR-TO-BASE BREAKDOWN VOLTAGE	V _{(BR)CBO}	I _C = -10μA, I _E = 0		-50	–	–	V
EMITTER-TO-SUBSTRATE BREAKDOWN VOLTAGE	V _{(BR)EIO}	I _{E1} = 10μA, I _B = 0, I _E = 0		-50	–	–	V
EMITTER-TO-BASE BREAKDOWN VOLTAGE	V _{(BR)EBO}	I _E = -10μA, I _C = 0		-40	–	–	V
COLLECTOR-TO-EMITTER SATURATION VOLTAGE	V _{CE(SAT)}	I _C = -1mA, I _B = -100μA	6	–	–	-0.33	V
BASE-TO-EMITTER SATURATION VOLTAGE	V _{BE(SAT)}	I _C = -1mA, I _B = -100μA	7	–	-0.7	–	V
BASE-TO-EMITTER VOLTAGE	V _{BE}	V _{CE} = -3 V, I _C = -100μA	8	-0.5	-0.6	-0.7	V
DC FORWARD-CURRENT TRANSFER RATIO	h _{FE}	V _{CE} = -3 V, I _C = -100μA V _{CE} = -3 V, I _C = -1 mA	9	30	60	–	
				40	–	–	
n-p-n/p-n-p TRANSISTOR PAIR Q3, Q4							
DC FORWARD-CURRENT TRANSFER RATIO	h _{FE}	V _{CE} (n-p-n) = 3V, I _C = 10mA V _{CE} (n-p-n) = 3V, I _C = 50mA	10	–	8000	–	
			10	–	6500	–	

ELECTRICAL CHARACTERISTICS (Cont'd.)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS Ambient Temperature (T _A) = 25°C Unless Otherwise Specified	FIG. NO.	LIMITS			UNITS
				Min.	Typ.	Max.	
PROGRAMMABLE UNIJUNCTION TRANSISTOR (PUT), Q1							
OFFSET VOLTAGE	V _T *	V _S = 10V, R _G = 10kΩ	11,22 ^a	0.2	—	0.7	V
		V _S = 10V, R _G = 1MΩ		0.2	—	0.7	
ANODE-TO-CATHODE ON-STATE VOLTAGE	V _F	I _F = 50mA	12	—	0.90	1.5	V
		I _F = 100mA		—	1	—	
PEAK OUTPUT VOLTAGE	V _{OM}	C = 0.22μF Anode Supply Voltage = 20V	13,23	—	10	—	V
PEAK-POINT CURRENT	I _P	V _S = 10V, R _G = 10kΩ	14,22 ^a	—	0.55	1	μA
		V _S = 10V, R _G = 1MΩ	—	—	0.015	0.15	
VALLEY-POINT CURRENT	I _V	V _S = 10V, R _G = 10kΩ	17,15	4	40	—	μA
		V _S = 10V, R _G = 1MΩ	16	—	—	25	
GATE REVERSE CURRENT	I _{GAO}	V _S = 30V	22 ^c	—	0.02	—	nA
GATE REVERSE CURRENT	I _{GKS}	Anode-To-Cathode Short, V _S , = 30V	22 ^d	—	0.2	—	nA
OUTPUT PULSE RISE TIME	t _r	Anode-Supply Voltage = 20V C = 0.22 μF	23	—	60	—	ns
SILICON CONTROLLED RECTIFIER (SCR), Q2							
PEAK OFF-STATE CURRENT: FORWARD	I _{DXM}	V _{DRXM} = 30V, R _{GK} = 1kΩ	24	—	—	2	μA
FORWARD DC VOLTAGE DROP	V _T	I _T = 50 mA	18	—	0.90	1.5	V
GATE-TO-SOURCE TRIGGER CURRENT	I _{GS}	T _A = 25°C	26	—	33	100	μA
		T _A = -55°C	26	—	50	—	
DC GATE-TRIGGER VOLTAGE	V _{GT}	V _L = 10V, R _L = 100Ω	19	—	0.55	0.75	V
HOLDING CURRENT	I _{HO}	R _{GK} = 1kΩ	20,24	—	1.2	—	mA
CRITICAL RATE-OF-RISE OF OFF-STATE VOLTAGE	dv/dt	EXPONENTIAL RISE, R _{GK} = 1kΩ, V _{DRXM} = 30V	25	—	150	—	V/μs
GATE-CONTROLLED TURN-ON TIME	t _{gt}	See Fig. 33	33	—	50	—	ns
CIRCUIT-COMMUTATED TURN-OFF TIME	t _q	See Fig. 33	33	—	10	—	μs
ZENER DIODE, Z1							
ZENER VOLTAGE	V _Z	I _Z = 10mA	21	7.2	8	8.8	V
ZENER IMPEDANCE	Z _Z	I _Z = 10mA, f = 1kHz		—	15	25	Ω
ZENER VOLTAGE TEMPERATURE COEFFICIENT	(ΔV _Z /V _Z)/ΔT	I _Z = 10mA		—	+0.05	—	%/°C
	ΔV _Z /ΔT			—	+4	—	mV/°C
ZENER-TO-SUBSTRATE BREAKDOWN VOLTAGE	V _{(BR)Z1O}	I _Z = 100μA TERM. 5 TO SUBSTRATE		50	80	—	V

* V_T = V_P - V_S (Fig. 22)

CA3097E

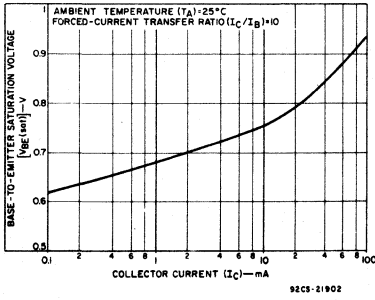


Fig. 2 - Base-to-emitter saturation voltage vs. collector current for n-p-n transistors Q3 & Q5.

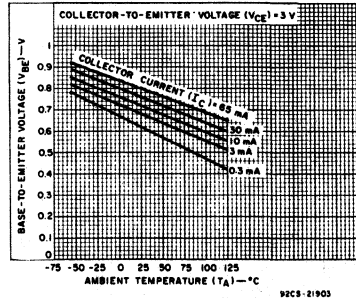


Fig. 3 - Base-to-emitter voltage vs. ambient temperature for n-p-n transistors Q3 & Q5.

TYPICAL CHARACTERISTICS

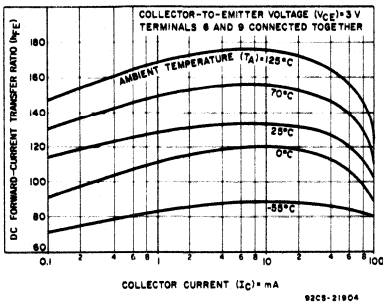


Fig. 4 - DC forward-current transfer ratio vs. collector current for n-p-n transistors Q3 & Q5.

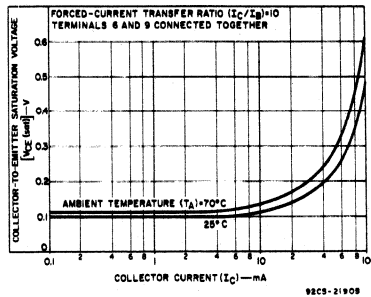


Fig. 5 - Collector-to-emitter saturation voltage vs. collector current for n-p-n transistors Q3 & Q5.

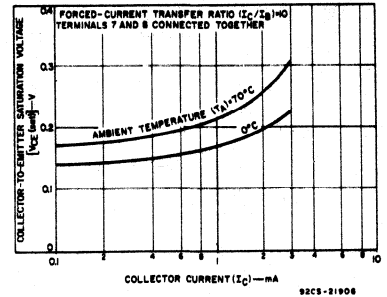


Fig. 6 - Collector-to-emitter saturation voltage vs. collector current for p-n-p transistor Q4.

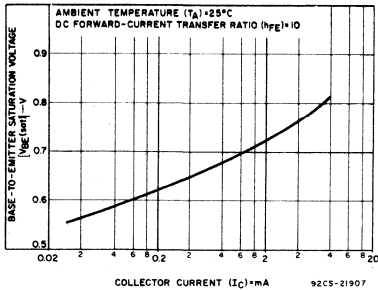


Fig. 7 - Base-to-emitter saturation voltage vs. collector current for p-n-p transistor Q4.

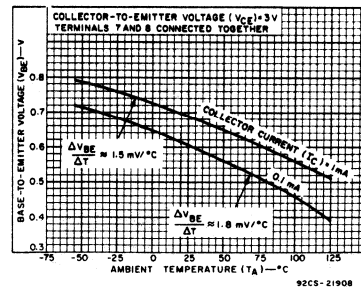


Fig. 8 - Base-to-emitter voltage vs. ambient temperature for p-n-p transistor Q4.

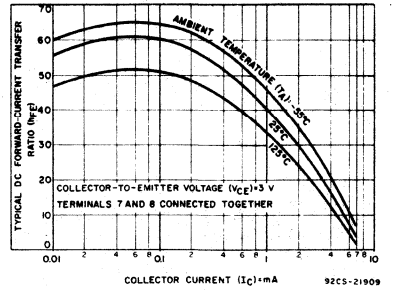


Fig. 9 - DC forward-current transfer ratio vs. collector current for p-n-p transistor Q4.

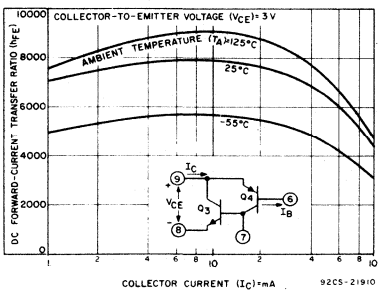


Fig. 10 - DC forward-current transfer ratio vs. collector current for transistor pair Q3, Q4.

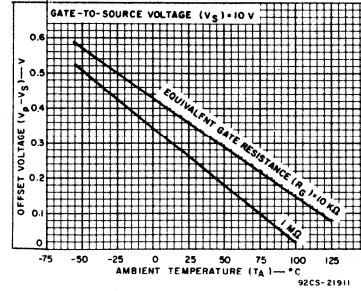


Fig. 11 - Offset voltage vs. ambient temperature for Q1 (PUT).

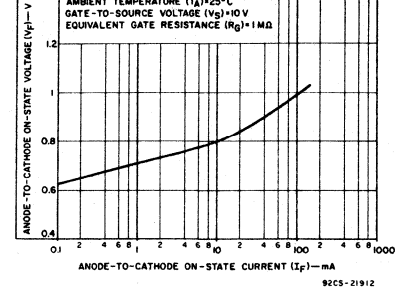


Fig. 12 - Anode-to-cathode on-state voltage vs. anode-to-cathode on-state current for Q1 (PUT).

TYPICAL CHARACTERISTICS (CONT'D)

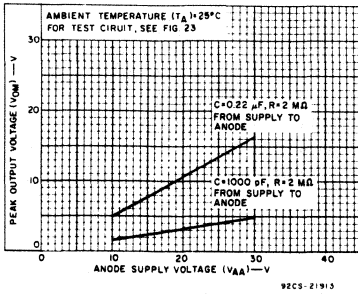


Fig. 13 — Peak output voltage vs. anode supply voltage for Q1 (PUT).

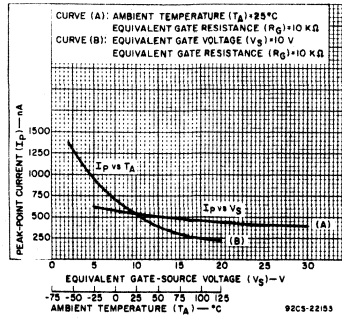


Fig. 14 — Peak-point current vs. gate-source voltage and ambient temperature for Q1 (PUT).

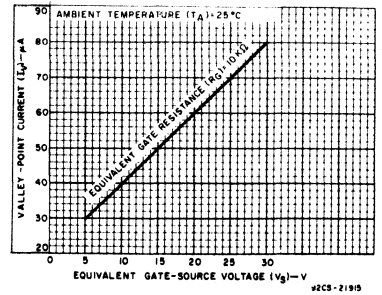


Fig. 15 — Valley-point current vs. gate-source voltage for Q1 (PUT).

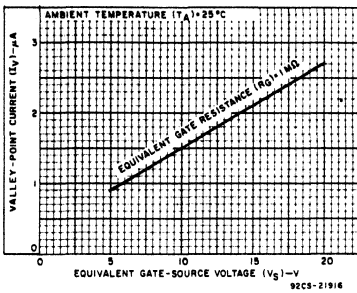


Fig. 16 — Valley-point current vs. gate-source voltage for Q1 (PUT).

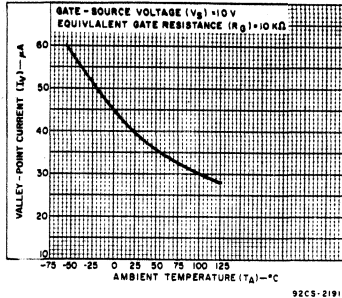


Fig. 17 — Valley-point current vs. ambient temperature for Q1 (PUT).

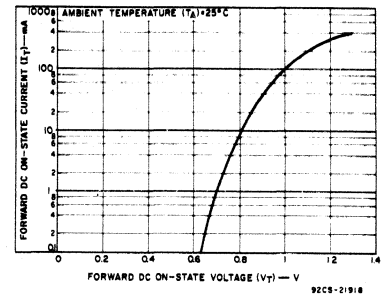


Fig. 18 — Forward DC on-state current vs. on-state voltage for Q2 (SCR).

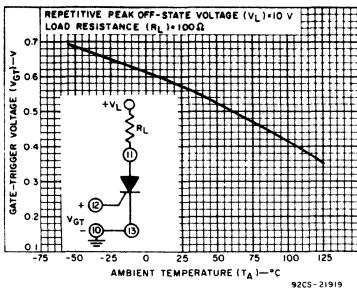


Fig. 19 — Gate-trigger voltage vs. ambient temperature for Q2 (SCR).

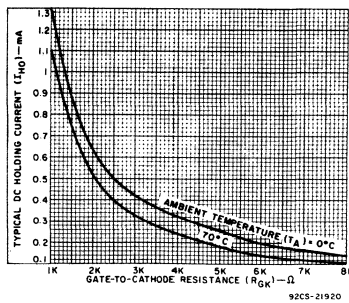


Fig. 20 — Typical DC holding current vs. gate-to-cathode resistance for Q2 (SCR).

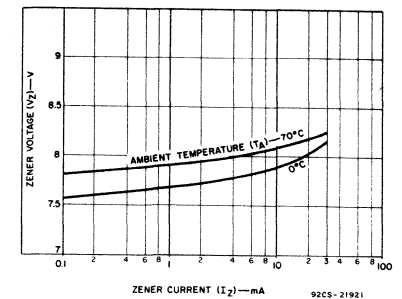


Fig. 21 — Zener voltage vs. zener current for Z1.

Linear Integrated Circuits

CA3097E

OPERATING CONSIDERATIONS FOR CA3097E

1. Composite p-n-p/n-p-n Transistors Q3, Q4 (See Fig. 3)

To use Q3 as an individual n-p-n transistor, join terminals no. 6 and no. 9 to disable p-n-p transistor Q4.

The appropriate terminal connections are then:

- Collector..... terminal 9
- Base terminal 7
- Emitter terminal 8

To use Q4 as an individual p-n-p transistor, join terminals no. 7 and no. 8 to disable n-p-n transistor Q3.

The appropriate terminal connections are then:

- Collector..... terminal 7
- Base terminal 6
- Emitter terminal 9

To use Q3 and Q4 as a composite use terminals 6, 7, 8, and 9 as required.

2. Programmable Unijunction Transistor Q1 (PUT)

The programmable unijunction transistor is essentially an anode-gate SCR. The volt-ampere characteristic of the device is shown in Fig. 22. When an equivalent Thevenin source (V_S , R_G), as shown in Fig. 22, is applied to the gate terminal the device will be "off" if the anode-voltage is negative with respect to the gate voltage. Under this condition, any current flow is exclusively leakage current. When the anode voltage be-

comes more positive than the gate voltage by an increment equal to the threshold voltage ($V_T = 0.4$ V typ.), the device can turn "on" only if the current available at the anode terminal is greater than the specified peak-point current. The PUT will then switch through its negative-resistance region to the "on" state (low anode-to-gate voltage). It should be noted that I_p is not the maximum current allowed through the device, but is the current required at the peak of the V-I curve. I_p is typically a very low value of current.

After the PUT has switched to its low-impedance state, the device will remain "on" if the anode-current (I_A) exceeds the valley-point current (I_V). If $I_A < I_V$, the PUT will switch back to its high-impedance "off" state. Thus, the PUT can be made to "latch" or recover, depending on I_V . Since I_V is a function of the "on"-state gate current (which depends on R_G and V_S) a choice of R_G and/or V_S will determine the operating mode, i.e., "off" state → "on" state or "off" state → "on" state → "off" state. The value of I_V increases directly as a function of V_G and inversely with R_G . The PUT in the CA3097E has a low I_p $I_p = 15$ nA at $V_S = 10$ V, $R_G = 1$ M Ω . This low value of I_p indicates that an extremely large value of anode-supply resistor, e.g. 60 M Ω (typ.), can be used in timing circuits requiring long RC time constants. This becomes important when considering the size of the external

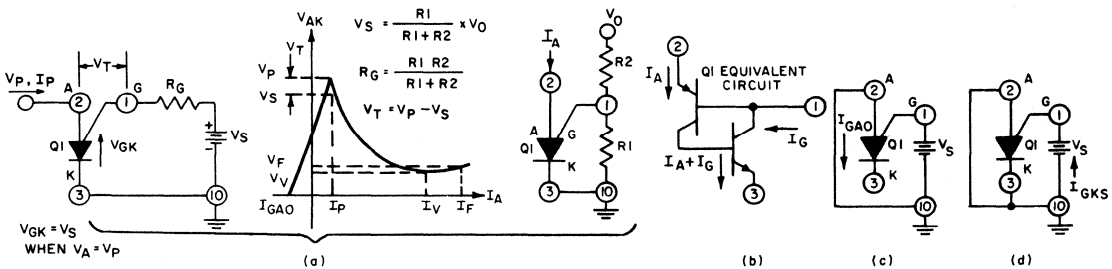


Fig. 22 — General anode characteristics for Q1 (PUT).

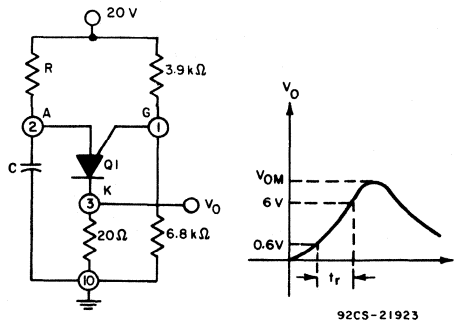


Fig. 23 — Output pulse characteristics for Q1 (PUT).

OPERATING CONSIDERATIONS (CONT'D)

timing capacitor to be used. Consequently, the use of the PUT in the CA3097E is advantageous since it has a lower I_p than most discrete PUT's.

Temperature Compensation of Switching Point

As described previously, the PUT will switch to its low-impedance state when its anode voltage is approximately a diode-drop above the gate voltage. Since the anode-to-gate threshold voltage vs. temperature characteristic is similar to that of a typical silicon-diode junction, a compensating series diode such as used in the circuit of Fig. 29 (Z1 connected as forward-biased diode) considerably reduces the effect of temperature on the switching point.

Bypassing Anode Current

If the PUT gate equivalent source is such that $I_A > I_V$, the PUT will remain "on". A method for turning the PUT off is by shunting current away from the anode until $I_A < I_V$. An example of this technique is the oscillator circuit of Fig. 29. Q3 transistor is turned "on" after the PUT fires and shunts current away from the anode, thereby forcing $I_A < I_V$. The PUT then turns "off" allowing C_T to recharge through R_T , to repeat the cycle.

Protecting The PUT Against Discharge Current Of The Capacitor

A current-limiting resistor in series with the PUT is normally required to dissipate capacitive discharge energy (see Figs. 23 and 29).

Silicon Controlled Rectifier, Q2 (SCR)

The SCR should be used with a 1 kΩ (or less) resistor connected between the cathode and gate terminals if the SCR is to be subjected to its maximum forward and reverse voltage ratings (V_{DXM} and V_{RXM}). Selecting a value for R_{GK} of 1 kΩ (or lower) increases the capability of the device to withstand greater dv/dt and increases the noise immunity of the SCR against false triggering at the gate. Practical considerations such as available current drive from the triggering devices (e.g., a PUT) will determine the lowest value of R_{GK} at which the SCR will fire with a $V_{GK} \approx 0.55$ V. With a value of 500Ω for R_{GK} , the trigger source must be capable of supplying 1.1 mA. R_{GK} should be non-inductive within the frequency band of the noise transients normally encountered in a particular application.

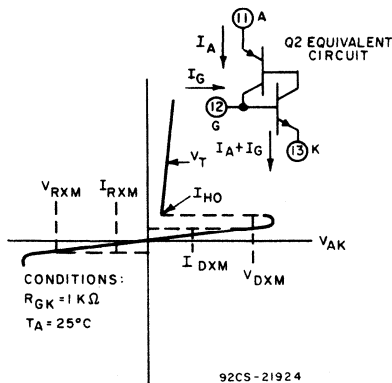


Fig. 24 - Principle voltage-current characteristics for Q2 (SCR).

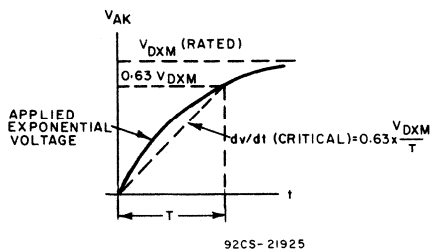
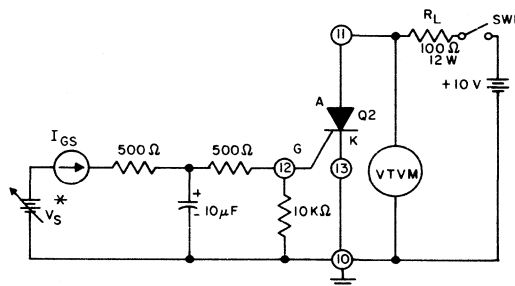


Fig. 25 - Definition of critical rate of rise of off-state voltage for Q2 (SCR).



WITH SWI CLOSED, INCREASE V_S UNTIL SCR FIRES (VTVM DROPS FROM 10V TO APPROXIMATELY 1V). I_{GS} (TRIGGER) IS MEASURED JUST PRIOR TO THIS TRIGGERING POINT. NOTE THAT I_{GS} MAY DECREASE AS V_S IS INCREASED DUE TO CURRENT DRAWN OUT OF THE GATE TERMINAL OF THE SCR AS IT TURNS ON. TO UNLATCH THE SCR OPEN SWI.

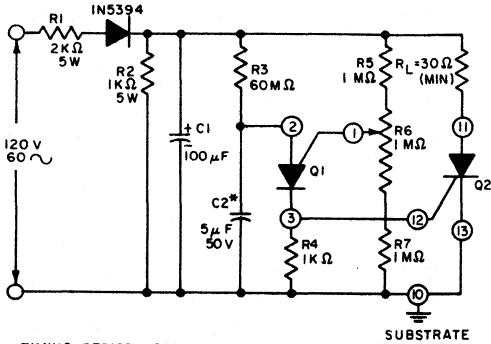
* V_S SHOULD BE CAPABLE OF SUPPLYING MILLIVOLT INCREMENTS NEAR THE TRIGGER POINT

Fig. 26 - Test circuit for determining I_{GS} in Q2 (SCR).

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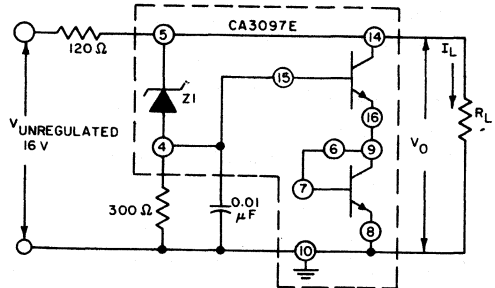
APPLICATIONS CIRCUITS



TIMING PERIOD \approx 200 SEC. WITH 1 MΩ POT CENTERED
 TIMING CYCLE BEGINS WHEN AC IS APPLIED
 * SPRAGUE TYPE 4308, 5 μF AT 50 V
 SPRAGUE TYPE 6308, 5 μF AT 50 V
 OR EQUIVALENT

92CS-21927

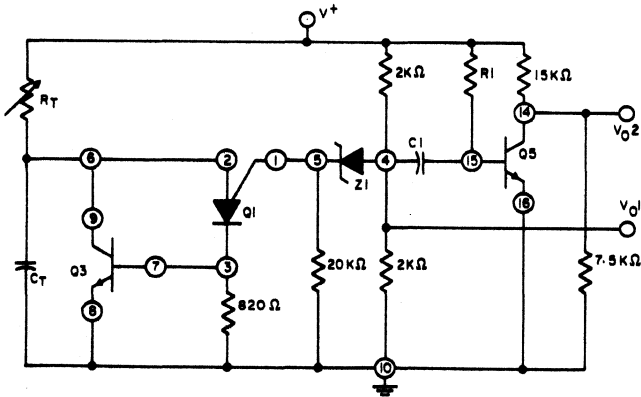
Fig. 27 - AC line-operated one-shot timer.



TYPICAL TEMPERATURE CHARACTERISTIC
 @ $R_L = 330 \Omega$ $\frac{\Delta V_0 / V_0}{\Delta T} \times 100 = \pm 0.01 \% / ^\circ C$
 TYP. LOAD REGULATION @ $I_L = 0$ TO 40 mA, $(\Delta V_0 / V_0) \times 100 = -3\%$ (NO LOAD TO FULL LOAD)
 TYP. LINE REGULATION @ $R_L = 330 \Omega$, $\frac{\Delta V_0 / V_0}{\Delta V_{UNREG}} \times 100 = \pm 0.55 \% / V$

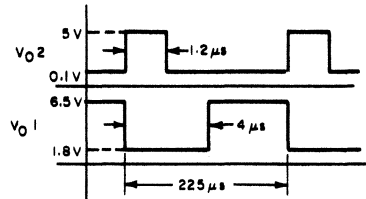
92CS-21928

Fig. 28 - Temperature-compensated shunt regulator.



PULSE RATE ADJUSTED BY VARYING R_T OR C_T
 OUTPUT PULSE WIDTH ADJUSTED BY $R_1 C_1$
 DIFFERENTIATING TIME CONSTANT

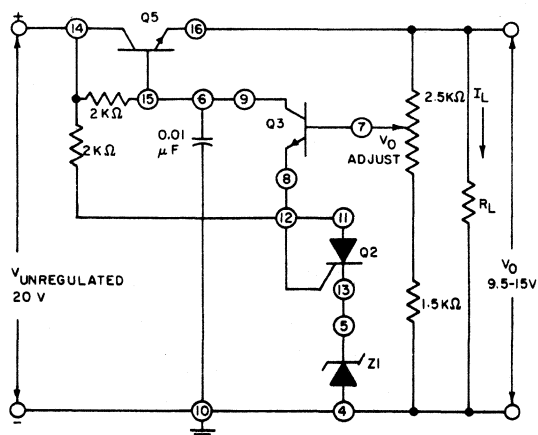
TYPICAL OPERATION FOR:
 $V^+ = 15 V$, $C_T = 0.1 \mu F$, $R_T = 4.3 k\Omega$
 $C_1 = 82 pF$, $R_1 = 60 k\Omega$



92CM-21929

Fig. 29 - Pulse generator.

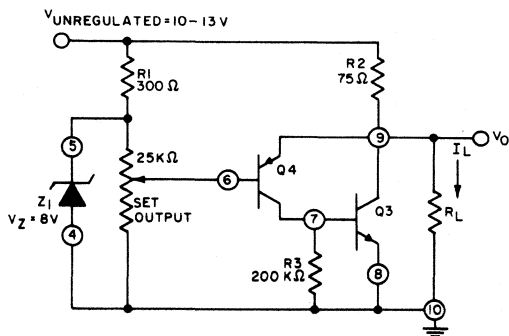
APPLICATIONS CIRCUITS



TYPICAL LOAD REGULATION @ $V_O = 12V, I_L = 0$ TO 40 mA
 $\frac{\Delta V_O}{V_O} \times 100 = \pm 0.4\%$ (NO LOAD TO FULL LOAD)
 TYPICAL LINE REGULATION @ $V_O = 12V$
 $\frac{\Delta V_O / V_O}{\Delta V_{UNREG.}} \times 100 = \pm 0.45\% / V$

92CS-21930

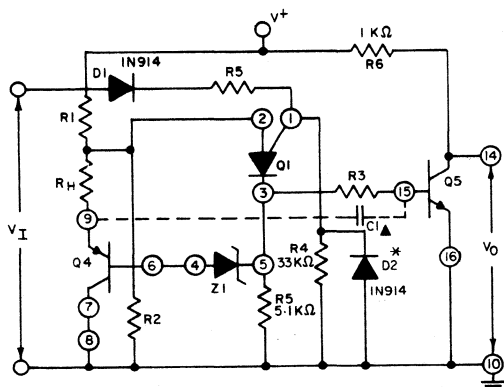
Fig. 30 — Series voltage regulator.



TYPICAL LOAD REGULATION @ $V_O = 7V, I_L = 0$ TO 40 mA
 $\frac{\Delta V_O}{V_O} \times 100 = -1.1\%$
 TYPICAL LINE REGULATION @ $V_O = 7V, I_L = 20$ mA
 $\frac{\Delta V_O}{V_O} = \pm 0.85\% / VOLT$
 $\frac{\Delta V_O}{\Delta V_{UNREGULATED}}$

92CS-21931

Fig. 31 — 5 to 7.5 V shunt regulator.



▲ OPTIONAL SPEED-UP CAPACITOR
 * REQUIRED IF V_I SWINGS BELOW GROUND

TYPICAL OPERATING CONDITIONS:

FREQUENCY IN = 0-10 KHz

SUPPLY VOLTAGE (V^+) = 15V

$R_1, R_2, R_H = 5.1 K\Omega$

$R_3 = 6.2 K\Omega, R_5 = 300\Omega$

$C_1 = 820 pF$

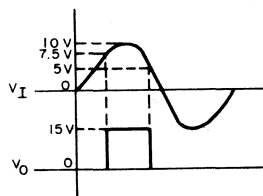
$V_{THU} = 7.5V, V_{THL} = 5V$

HYSTERESIS VOLTAGE = 2.5V

UPPER THRESHOLD VOLTAGE (V_{THU}) $\approx V^+ \frac{R_2}{R_1 + R_2}$

LOWER THRESHOLD VOLTAGE (V_{THL}) $\approx (V^+) \frac{(R_2 R_H)}{R_2 R_H + R_1}$

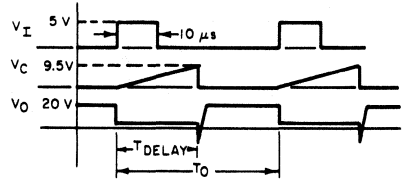
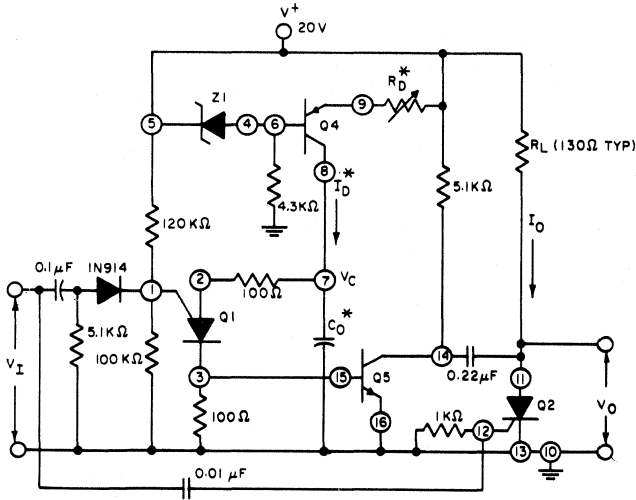
HYSTERESIS VOLTAGE = $V_{THU} - V_{THL}$



92CM-21932

Fig. 32 — Schmitt trigger.

APPLICATIONS CIRCUITS (CONT'D)

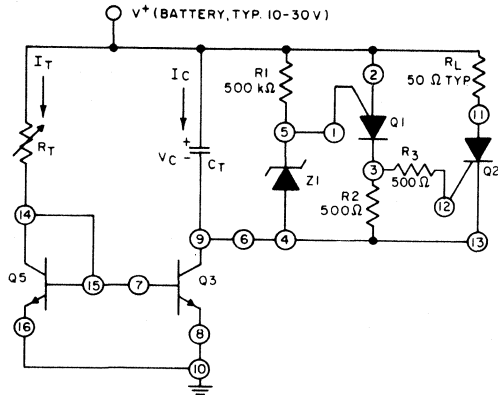


* MONOSTABLE DELAY TIME SET BY ADJUSTMENT OF I_D (VARY R_D) OR BY C_D . I_D MUST BE GREATER THAN I_V OF Q1 (PUT) FOR MONOSTABLE OPERATION.

Q2 (SCR) SWITCHING TIMES:
 GATE-CONTROLLED TURN-ON TIME (t_{q1}) = 50 ns (TYP)
 CIRCUIT-COMMUTATED TURN-OFF TIME (t_q) = 10 μs (TYP)

92CM-21933

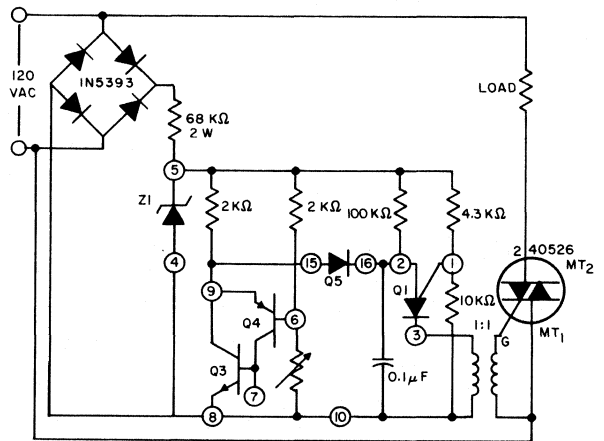
Fig. 33 - Monostable multivibrator with variable delay.



T_{OFF} = TIMING PERIOD (NO LOAD CURRENT)
 PUT FIRES WHEN $V_C \approx 8V$
 $V_C = \frac{I_C (T_{OFF})}{C_T}$, $I_C \approx I_T$ (Q3, Q5 MATCHED)
 I_T SET BY ADJUSTING R_T , $I_T \approx \frac{V^+ - 0.7}{R_T}$
 T_{ON} = CAPACITOR DISCHARGE TIME THROUGH LOAD. LOAD TURNS OFF WHEN SCR ANODE CURRENT FALLS BELOW HOLDING CURRENT (I_{HO}). TYPICAL $I_{HO} = 1.2mA$
 EXAMPLE: FOR TIMING PERIOD OF 8.3 MIN
 $C_T = 1000 \mu F$, $I_T = 16 \mu A$
 $R_T = \frac{V^+ - 0.7}{I_T}$ (FOR $V^+ = 16V$, $R_T \approx 1M\Omega$)

92CS-21934

Fig. 34 - Low-current-drain battery-operated long interval astable timer.

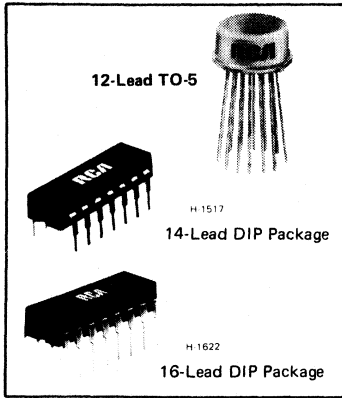


NOTE: SHORT TERMINAL 15 TO 14 WHEN USING Q5 AS A DIODE
 92CS-22178

Fig. 35 - Phase control circuit.

CA3118, CA3146, CA3183 Types

High-Voltage Transistor Arrays



Applications

- General use in signal processing systems in DC through VHF range
- Custom designed differential amplifiers
- Temperature compensated amplifiers
- Lamp and relay drivers (CA3183AE, E)
- Thyristor firing (CA3183AE, E)

Features

- Matched general-purpose transistors
- V_{BE} matched $\pm 5mV$ max.
- Operation from DC to 120 MHz (CA3118AT, T; CA3146AE, E)
- Low-noise figure: 3.2dB typ. at 1kHz (CA3118AT, T; CA3146AE, E)
- High I_C : 75mA max. (CA3183AE, E)

RCA-CA3118AT, CA3118T, CA3146AE, CA3146E, CA3183AE, and CA3183E* are general-purpose high-voltage silicon n-p-n transistor arrays on a common monolithic substrate.

Types CA3118AT and CA3118T consist of four transistors with two of the transistors connected in a Darlington configuration. These types are well suited for a wide variety of applications in low-power systems in the DC through VHF range. Both types are supplied in a hermetically sealed 12-lead TO-5 type package and operate over the full military temperature range. (CA3118AT and CA3118T are high-voltage versions of the popular predecessor type CA3018.

Types CA3146AE and CA3146E consist of five transistors with two of the transistors connected to form a differentially-connected pair. These types are recommended for low-power applications in the DC through VHF range. Both types are supplied in a 14-lead dual-in-line plastic package and operate over the ambient temperature range of $-40^{\circ}C$ to $+85^{\circ}C$. (CA3146AE and CA3146E are high-voltage versions of the popular predecessor type CA3046.)

Types CA3183AE and CA3183E consist of five high-current transistors with independent connections for each transistor. In addition two of these transistors (Q1 and Q2) are matched at low-current (i.e. 1mA) for applications where offset parameters are of special importance. A special substrate terminal is also included for greater flexibility in circuit design. Both types are supplied in a 16-lead dual-in-line plastic package and operate over the ambient temperature range of $-40^{\circ}C$ to $+85^{\circ}C$. (CA3183AE and CA3183E are high-voltage versions of the popular predecessor type CA3083.)

The types with an "A" suffix are premium versions of their non-"A" counterparts and feature tighter control of breakdown voltages making them more suitable for higher voltage applications.

For detailed application information, see companion Application Note, ICAN-5296 "Application of the RCA CA3018 Integrated Circuit Transistor Array."

* Formerly Developmental Types Nos.

CA3118AT	- TA6091	CA3146E	- TA6181
CA3118T	- TA6182	CA3183AE	- TA6094
CA3146AE	- TA6084	CA3183E	- TA6183

TYPE	P_T [●] max. mW	I_C max. mA	V_{CEO} max. V	V_{CBO} max. V	V_{CE} sat. at 10 mA typ. V	h_{FE} at 1 mA, & $V_{CE}=5V$ typ.	V_{IO} / I_{IO}		T_A Range (Operating) $^{\circ}C$
							Diff. Pair at 1 mA		
							max. mV	max. μA	
VALUES APPLY FOR EACH TRANSISTOR									
CA3118AT	300	50	40	50	0.33	95	± 5	2	$-55 - +125$
CA3118T	300	50	30	40	0.33	95	± 5	2	$-55 - +125$
CA3146AE	300	50	40	50	0.33	95	± 5	2	$-40 - +85$
CA3146E	300	50	30	40	0.33	95	± 5	2	$-40 - +85$
CA3183AE	500	75	40	50	0.16	75	± 5	2.5	$-40 - +85$
CA3183E	500	75	30	40	0.16	75	± 5	2.5	$-40 - +85$

● Caution on Total Package Power Dissipation: The maximum total package dissipation rating for the CA3118 Series circuits is 450 mW at temperatures up to $+85^{\circ}C$, then derate linearly at 5 mW/ $^{\circ}C$. The maximum total package dissipation rating for the CA3146 and CA3183 Series circuits is 750 mW at temperatures up to $+55^{\circ}C$, then derate linearly at 6.67 mW/ $^{\circ}C$.

Linear Integrated Circuits

CA3118, CA3146, CA3183 Types

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

Power Dissipation:

Any one transistor —		
CA3118AT, CA3118T, CA3146AE, CA3146E	300	mW
CA3183AE, CA3183E	500	mW
Total package —		
Up to 85°C (CA3118AT, CA3118T)	450	mW
Up to 55°C (CA3146AE, CA3146E, CA3183AE, CA3183E)	750	mW
Above 85°C (CA3118AT, CA3118T)	derate linearly 5	mW/ $^\circ\text{C}$
Above 55°C (CA3146AE, CA3146E, CA3183AE, CA3183E)	derate linearly 6.67	mW/ $^\circ\text{C}$

Ambient Temperature Range:

Operating —		
CA3118AT, CA3118T	-55 to +125	$^\circ\text{C}$
CA3146AE, CA3146E, CA3183AE, CA3183E	-40 to +85	$^\circ\text{C}$
Storage (all types)		
	-65 to +150	$^\circ\text{C}$

The following ratings apply for each transistor in the device:

Collector-to-Emitter Voltage (V_{CE0}):		
CA3118AT, CA3146AE, CA3183AE	40	V
CA3118T, CA3146E, CA3183E	30	V
Collector-to-Base Voltage (V_{CBO}):		
CA3118AT, CA3146AE, CA3183AE	50	V
CA3118T, CA3146E, CA3183E	40	V
Collector-to-Substrate Voltage (V_{C10}): ■		
CA3118AT, CA3146AE, CA3183AE	50	V
CA3118T, CA3146E, CA3183E	40	V
Emitter-to-Base Voltage (V_{EBO}) all types		
	5	V
Collector Current —		
CA3118AT, CA3118T, CA3146AE, CA3146E	50	mA
CA3183AE, CA3183E	75	mA
Base Current (I_B) — CA3183AE, CA3183E		
	20	mA

■ The collector of each transistor is isolated from the substrate by an integral diode. The substrate must be connected to a voltage which is more negative than any collector voltage in order to maintain isolation between transistors and provide normal transistor action. To avoid undesired coupling between transistors, the substrate terminal should be maintained at either DC or signal (AC) ground. A suitable bypass capacitor can be used to establish a signal ground.

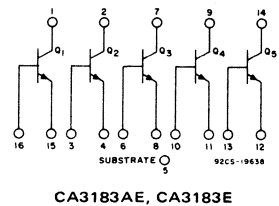
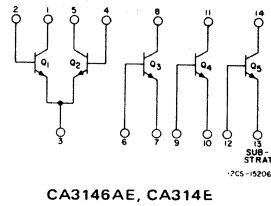
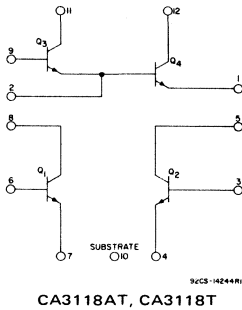


Fig. 1 — Schematic diagrams of high-voltage arrays.

COMPARISON OF RELATED PREDECESSOR TYPE WITH TYPES IN THIS DATA BULLETIN

	DATA FILE NO.	V_{CE0} min.	V_{CBO} min.	V_{CE} sat. typ. V	V_{BE} typ. V	I_C max. mA	C_{CB} typ. pF	C_{CI} typ. pF	C_{EB} typ. pF
				$I_C=10\text{ mA}$	$I_C=1\text{ mA}$				
CA3018	338	15	20	0.23	0.715	50	0.58	2.8	0.6
CA3018A	338	15	20	0.23	0.715	50	0.58	2.8	0.6
CA3118AT		40	50	0.33	0.730	50	0.37	2.2	0.7
CA3118T		30	40	0.33	0.730	50	0.37	2.2	0.7
CA3046	341	15	20	0.23	0.715	50	0.58	2.8	0.6
CA3146AE		40	50	0.33	0.730	50	0.37	2.2	0.7
CA3146E		30	40	0.33	0.730	50	0.37	2.2	0.7
CA3083	481	15	20	0.4	0.74	100	—	—	—
CA3183AE		40	50	1.7	0.75	75	—	—	—
CA3183E		30	40	1.7	0.75	75	—	—	—

NOTE: Related predecessor types are shown in shaded areas.

CA3118, CA3146, CA3183 Types

STATIC ELECTRICAL CHARACTERISTICS – CA3118 and CA3146 Series

CHARACTERISTICS	SYMBOL	TEST CONDITIONS			LIMITS						UNITS
		T _A = 25°C	Typ. Char. Curve Fig. No.	CA3118AT, CA3146AE			CA3118T, CA3146E				
				Min.	Typ.	Max.	Min.	Typ.	Max.		
For Each Transistor :											
Collector-to-Base Breakdown Voltage	V _{(BR)CBO}	I _C = 10 μA, I _E = 0	–	50	72	–	40	72	–	V	
Collector-to-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C = 1mA, I _B = 0	–	40	56	–	30	56	–	V	
Collector-to-Substrate Breakdown Voltage	V _{(BR)CIO}	I _{C1} = 10μA, I _B = 0 I _E = 0	–	50	72	–	40	72	–	V	
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E = 10μA, I _C = 0	–	5	7	–	5	7	–	V	
Collector-Cutoff Current	I _{CEO}	V _{CE} = 10V, I _B = 0	2	–	see curve	5	–	see curve	5	μA	
Collector-Cutoff Current	I _{CBO}	V _{CB} = 10V, I _E = 0	3	–	0.002	100	–	0.002	100	nA	
DC Forward-Current Transfer Ratio	h _{FE}	V _{CE} =5V	I _C =10mA	4	–	85	–	–	85	–	–
			I _C =1mA	4	30	100	–	30	100	–	
			I _C =10μA	4	–	90	–	–	90	–	
Base-to-Emitter Voltage	V _{BE}	V _{CE} = 3V, I _C = 1 mA	5	0.63	0.73	0.83	0.63	0.73	0.83	V	
Collector-to-Emitter Saturation Voltage	V _{CEsat}	I _C = 10mA, I _B = 1mA	6	–	0.33	–	–	0.33	–	V	
For transistors Q3 and Q4 (Darlington Configuration):											
Collector-Cutoff Current	CA3118AT and CA3118T only	I _{CEO}	V _{CE} = 10V, I _B = 0	–	–	–	5	–	–	–	μA
DC Forward-Current Transfer Ratio		h _{FE}	V _{CE} = 5V, I _C = 1 mA	7	1500	9000	–	1500	9000	–	–
Base-to-Emitter (Q3 to Q4)	V _{BE}	V _{CE} =5V	I _E = 10mA	8	–	1.46	–	–	1.46	–	V
			I _E = 1mA	8,9	–	1.32	–	–	1.32	–	
Magnitude of Base-to-Emitter Temperature Coefficient	$\frac{\Delta V_{BE}}{\Delta T}$	V _{CE} = 5V, I _E = 1 mA	–	–	4.4	–	–	4.4	–	mV/°C	
For transistors Q1 and Q2 (AS a Differential Amplifier):											
Magnitude of Input Offset Voltage $ V_{BE1} - V_{BE2} $	V _{IO}	V _{CE} = 5V, I _E = 1 mA	10,11	–	0.48	5	–	0.48	5	mV	
Magnitude of h _{FE} Ratio	CA3118AT and CA3118T only	V _{CE} = 5V, I _{C1} = I _{C2} = 1mA	–	0.9	1.0	1.1	0.9	1.0	1.1	–	
Magnitude of Base-to-Emitter Temperature Coefficient	$\frac{\Delta V_{BE}}{\Delta T}$	V _{CE} = 5V, I _E = 1 mA	–	–	1.9	–	–	1.9	–	mV/°C	
Magnitude of V _{IO} (V _{BE1} - V _{BE2}) Temperature Coefficient	$\frac{\Delta V_{IO}}{\Delta T}$	V _{CE} = 5V, I _{C1} = I _{C2} = 1 mA	–	–	1.1	–	–	1.1	–	μV/°C	
Magnitude of Input Offset Current $ I_{IO1} - I_{IO2} $	CA3146AE and CA3146E only	I _{IO}	V _{CE} = 5V, I _{C1} = I _{C2} = 1 mA	12	–	0.3	2	–	0.3	2	μA

Linear Integrated Circuits

CA3118, CA3146, CA3183 Types

DYNAMIC ELECTRICAL CHARACTERISTICS – CA3118 and CA3146 Series

CHARACTERISTICS	SYMBOL	TEST CONDITIONS		CA3118AT CA3146AE			CA3118T CA3146E			UNITS								
		T _A = 25°C	Typ. Char. Curve Fig.No.	Min.	Typ.	Max.	Min.	Typ.	Max.									
Low Frequency Noise Figure	NF	f = 1kHz, V _{CE} = 5V, I _C = 100μA, Source resistance = 1 kΩ	14	–	3.25	–	–	3.25	–	dB								
Low-Frequency, Small-Signal Equivalent-Circuit Characteristics:		f = 1kHz, V _{CE} = 5V, I _C = 1mA																
Forward-Current Transfer Ratio	h _{fe}										16	–	100	–	–	100	–	–
Short-Circuit Input Impedance	h _{ie}										16	–	2.7	–	–	3.5	–	kΩ
Open-Circuit Output Impedance	h _{oe}										16	–	15.6	–	–	15.6	–	μmho
Open-Circuit Reverse Voltage Transfer Ratio	h _{re}		16	–	1.8x10 ⁻⁴	–	–	1.8x10 ⁻⁴	–	–								
Admittance Characteristics:		f = 1MHz, V _{CE} = 5V, I _C = 1mA																
Forward Transfer Admittance	Y _{fe}										17	–	31-j1.5	–	–	31-j1.5	–	mmho
Input Admittance	Y _{ie}										18	–	0.35+j0.04	–	–	0.3+j0.04	–	mmho
Output Admittance	Y _{oe}										19	–	0.001+j0.03	–	–	0.001+j0.03	–	mmho
Reverse Transfer Admittance	Y _{re}		20		See curve		See curve		mmho									
Gain-Bandwidth Product	f _T	V _{CE} = 5V, I _C = 3mA	21	300	500	–	300	500	–	MHz								
Emitter-to-Base Capacitance	C _{EB}	V _{EB} = 5V, I _E = 0	22	–	0.70	–	–	0.70	–	pF								
Collector-to-Base Capacitance	C _{CB}	V _{CB} = 5V, I _C = 0	22	–	0.37	–	–	0.37	–	pF								
Collector-to-Substrate Capacitance	C _{CI}	V _{CI} = 5V, I _C = 0	22	–	2.2	–	–	2.2	–	pF								

STATIC ELECTRICAL CHARACTERISTICS – CA3183 Series

CHARACTERISTICS	SYMBOL	TEST CONDITIONS		LIMITS						UNITS
		T _A = 25°C	Typ. Char. Curve Fig. No.	CA3183AE			CA3183E			
				Min.	Typ.	Max.	Min.	Typ.	Max.	
For Each Transistor:										
Collector-to-Base Breakdown Voltage	V _{(BR)CBO}	I _C = 100μA, I _E = 0	–	50	–	–	40	–	–	V
Collector-to-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C = 1mA, I _B = 0	–	40	–	–	30	–	–	V
Collector-to-Substrate Breakdown Voltage	V _{(BR)CIO}	I _{C1} = 100μA, I _B = 0, I _E = 0	–	50	–	–	40	–	–	V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E = 500μA, I _C = 0	–	5	–	–	5	–	–	V
Collector-Cutoff Current	I _{CEO}	V _{CE} = 10V, I _B = 0	23	–	–	10	–	–	10	μA
Collector-Cutoff Current	I _{CBO}	V _{CB} = 10V, I _E = 0	24	–	–	1	–	–	1	μA
DC Forward-Current Transfer Ratio	h _{FE}	V _{CE} = 3V, I _C = 10mA	25,26	40	–	–	40	–	–	–
		V _{CE} = 5V, I _C = 50mA	–	40	–	–	40	–	–	–
Base-to-Emitter Voltage	V _{BE}	V _{CE} = 3V, I _C = 10mA	27	0.65	0.75	0.85	0.65	0.75	0.85	V
Collector-to-Emitter Saturation Voltage	*V _{CEsat}	I _C = 50mA, I _B = 5mA	28	–	1.7	3.0	–	1.7	3.0	V
For Transistors Q1 and Q2 (As a Differential Amplifier):										
Absolute Input Offset Voltage	V _{IO}	V _{CE} = 3V, I _C = 1mA	29	–	0.47	5	–	0.47	5	mV
Absolute Input Offset Current	I _{IO}		30	–	0.78	2.5	–	0.78	2.5	μA

* A maximum dissipation of 5 transistors x 150mW = 750mW is possible for a particular application.

CA3118, CA3146, CA3183 Types

TYPICAL STATIC CHARACTERISTICS CURVES – CA3118 and CA3146 SERIES

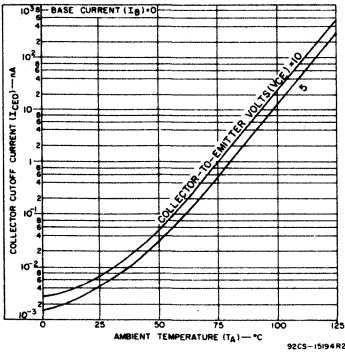


Fig. 2 – I_{CEO} vs. T_A for any transistor.

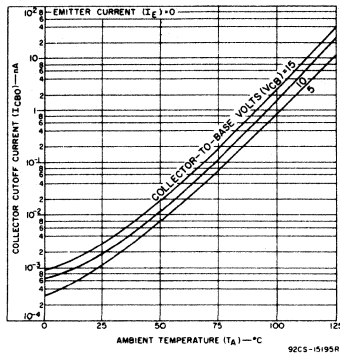


Fig. 3 – I_{CBO} vs. T_A for any transistor.

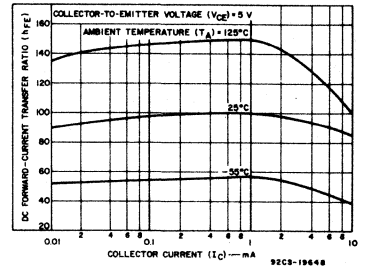


Fig. 4 – h_{FE} vs. I_C for any transistor.

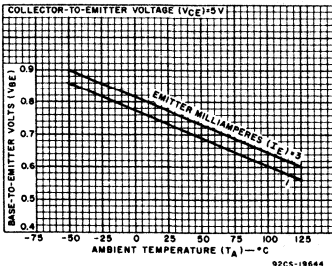


Fig. 5 – V_{BE} vs. T_A for any transistor.

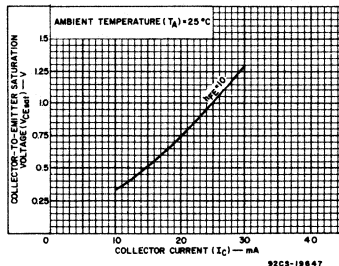


Fig. 6 – $V_{CE\ sat}$ vs. I_C for any transistor.

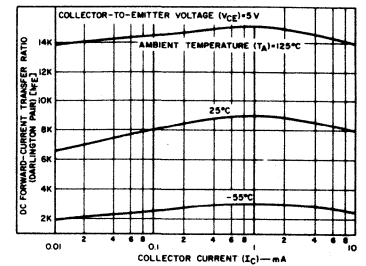


Fig. 7 – h_{FE} vs. I_C for Darlington pair (Q3 and Q4) for types CA3118AT and CA3118T.

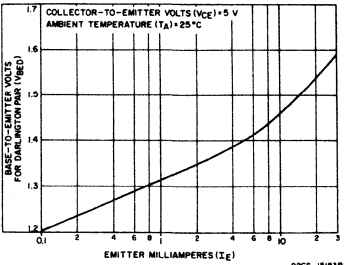


Fig. 8 – V_{BE} vs. I_E for Darlington pair (Q3 and Q4).

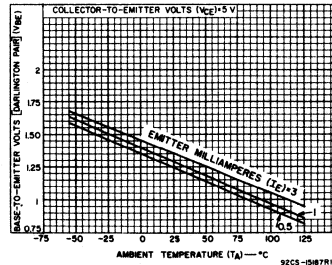


Fig. 9 – V_{BE} vs. T_A for Darlington pair (Q3 and Q4).

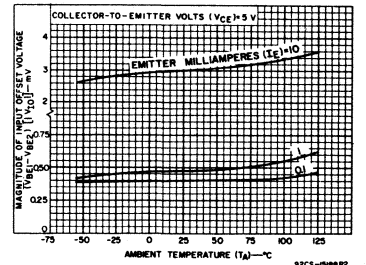


Fig. 10 – V_{I0} vs. T_A for Q1 and Q2.

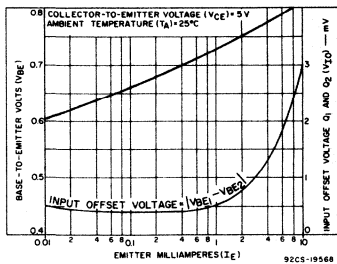


Fig. 11 – V_{BE} and V_{I0} vs. I_E for Q1 and Q2.

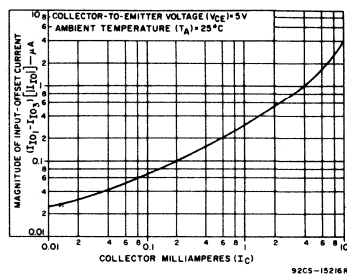


Fig. 12 – I_{I0} vs. I_C (Q1 and Q2) for types CA3146AE and CA3146E.

Linear Integrated Circuits

CA3118, CA3146, CA3183 Types

TYPICAL DYNAMIC CHARACTERISTICS CURVES (FOR ANY TRANSISTOR) – CA3118, CA3146 SERIES

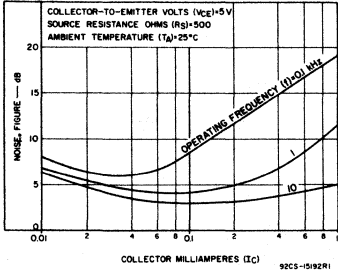


Fig. 13 — NF vs. I_C @ $R_S = 500 \Omega$.

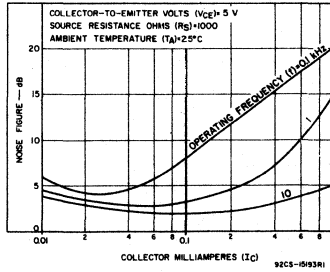


Fig. 14 — NF vs. I_C @ $R_S = 1k \Omega$.

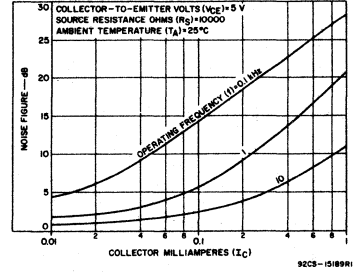


Fig. 15 — NF vs. I_C @ $R_S = 10k \Omega$.

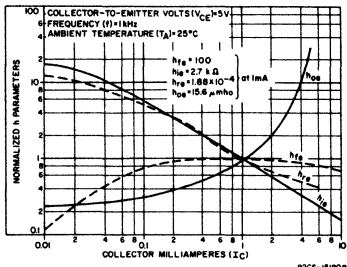


Fig. 16 — h_{fe} , h_{ie} , h_{oe} , h_{re} vs. I_C .

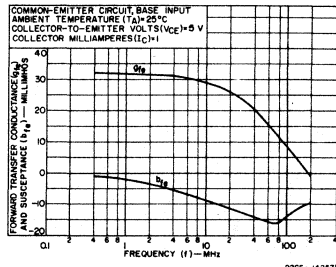


Fig. 17 — y_{fe} vs. f .

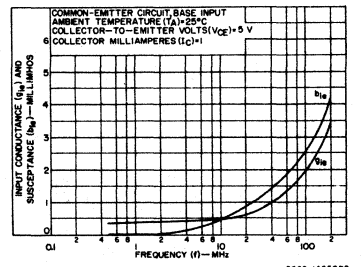


Fig. 18 — y_{ie} vs. f .

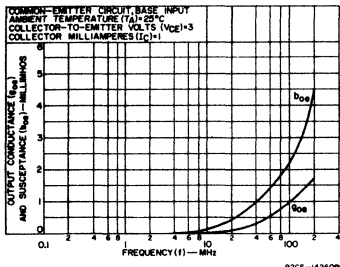


Fig. 19 — Y_{oe} vs. f .

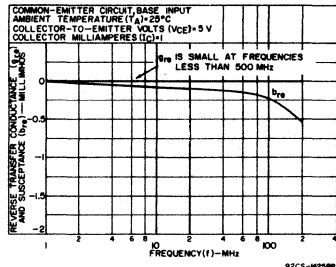


Fig. 20 — Y_{re} vs. f .

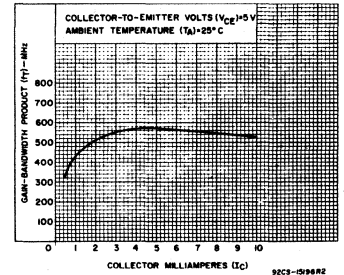


Fig. 21 — f_t vs. I_C

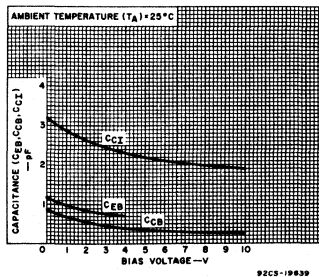


Fig. 22 — C_{EB} , C_{CB} , C_{CI} vs. bias voltage

CA3118, CA3146, CA3183 Types

TYPICAL STATIC CHARACTERISTICS CURVES — CA3183 SERIES

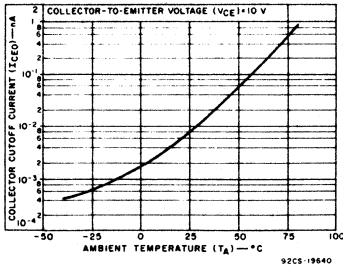


Fig. 23 — I_{CEO} vs. T_A for any transistor.

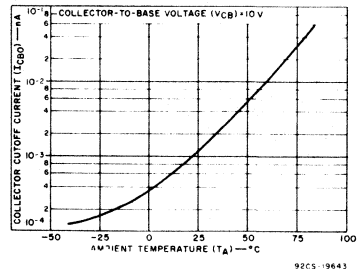


Fig. 24 — I_{CBO} vs. T_A for any transistor.

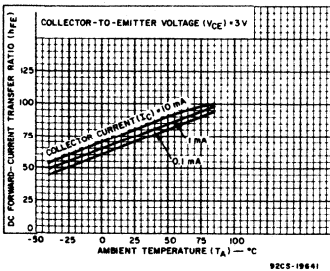


Fig. 25 — h_{FE} vs. T_A for any transistor.

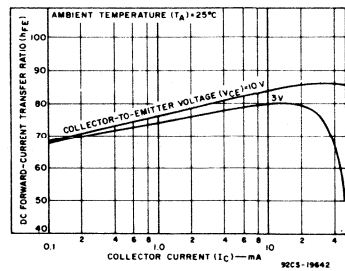


Fig. 26 — h_{FE} vs. I_C for any transistor.

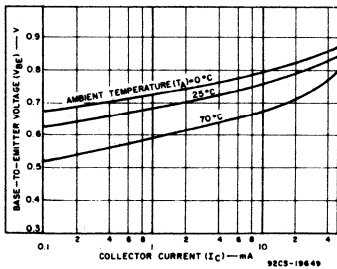


Fig. 27 — V_{BE} vs. I_C for any transistor.

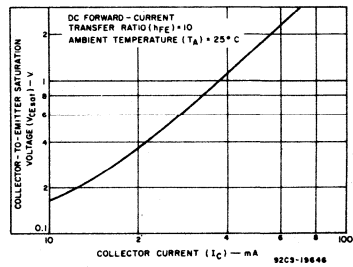


Fig. 28 — $V_{CE sat}$ vs. I_C for any transistor.

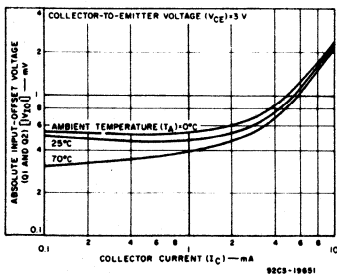


Fig. 29 — $|V_{IO}|$ vs. I_C for differential amplifier (Q1 and Q2).

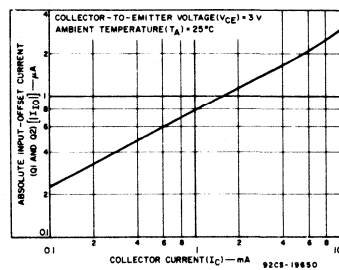
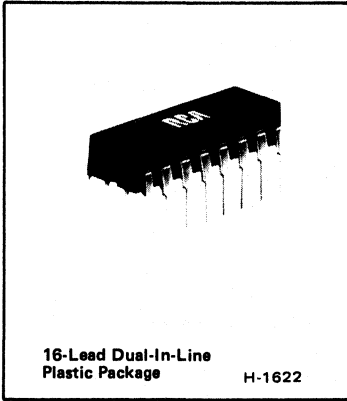


Fig. 30 — $|I_{IO}|$ vs. I_C for differential amplifier (Q1 and Q2).

CA3127E



High-Frequency N-P-N Transistor Array

For Low-Power Applications at Frequencies up to 500 MHz

Features:

- Gain-bandwidth product (f_T) > 1 GHz
- Power gain = 30 dB (typ.) at 100 MHz
- Noise figure = 3.5 dB (typ.) at 100 MHz
- Five independent transistors on a common substrate

Applications:

- VHF amplifiers
- Multifunction combinations - RF/mixer/oscillator
- Sense amplifiers
- Synchronous detectors
- VHF mixers
- IF converter
- IF amplifiers
- Synthesizers
- Cascade amplifiers

RCA-CA3127E* consists of five general-purpose silicon n-p-n transistors on a common monolithic substrate. Each of the completely isolated transistors exhibits low $1/f$ noise and a value of f_T in excess of 1 GHz, making the CA3127E useful from dc to 500 MHz. Access is provided to each of the terminals for the individual transistors and a separate substrate connection has been provided for maximum application flexibility. The monolithic construction of the CA3127E provides close electrical and thermal matching of the five transistors.

The CA3127E is supplied in a 16-lead dual-in-line plastic package and operates over the full military temperature range of -55 to +125°C.

*Formerly RCA Dev. No. TA6206.

MAXIMUM RATINGS, Absolute-Maximum Values:

POWER DISSIPATION, P_D :

Any one transistor	85 mW
Total Package:	
For T_A up to 75°C	425 mW
For $T_A > 75^\circ\text{C}$ Derate Linearly at	6.67 mW/°C

AMBIENT TEMPERATURE RANGE:

Operating	-55 to +125°C
Storage	-65 to +125°C

LEAD TEMPERATURE (DURING SOLDERING):

At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10 seconds max.	+265°C
---	--------

The following ratings apply for each transistor in the device:

Collector-to-Emitter Voltage, V_{CE0}	15 V
Collector-to-Base Voltage, V_{CBO}	20 V
Collector-to-Substrate Voltage, V_{C10} *	20 V
Collector Current, I_C	20 mA

*The collector of each transistor of the CA3127E is isolated from the substrate by an integral diode. The substrate (terminal 5) must be connected to the most negative point in the external circuit to maintain isolation between transistors and to provide for normal transistor action.

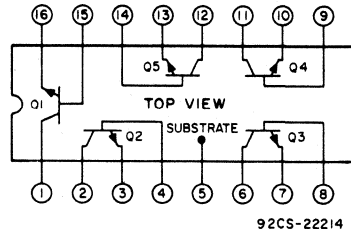


Fig. 1 — Schematic diagram of CA3127E.

STATIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

CHARACTERISTICS	TEST CONDITIONS	LIMITS			UNITS	
		Min.	Typ.	Max.		
For Each Transistor:						
Collector-to-Base Breakdown Voltage	$I_C = 10\ \mu\text{A}, I_E = 0$	20	32	—	V	
Collector-to-Emitter Breakdown Voltage	$I_C = 1\ \text{mA}, I_B = 0$	15	24	—	V	
Collector-to-Substrate Breakdown Voltage	$I_{C1} = 10\ \mu\text{A}, I_B = 0, I_E = 0$	20	60	—	V	
Emitter-to-Base Breakdown Voltage*	$I_E = 10\ \mu\text{A}, I_C = 0$	4	5.7	—	V	
Collector-Cutoff-Current	$V_{CE} = 10\ \text{V}, I_B = 0$	—	—	0.5	μA	
Collector-Cutoff-Current	$V_{CB} = 10\ \text{V}, I_E = 0$	—	—	40	nA	
DC Forward-Current Transfer Ratio	$V_{CE} = 6\ \text{V}$	$I_C = 5\ \text{mA}$	35	88	—	
		$I_C = 1\ \text{mA}$	40	90	—	
		$I_C = 0.1\ \text{mA}$	35	85	—	
Base-to-Emitter Voltage	$V_{CE} = 6\ \text{V}$	$I_C = 5\ \text{mA}$	0.71	0.81	0.91	V
		$I_C = 1\ \text{mA}$	0.66	0.76	0.86	
		$I_C = 0.1\ \text{mA}$	0.60	0.70	0.80	
Collector-to-Emitter Saturation Voltage	$I_C = 10\ \text{mA}, I_B = 1\ \text{mA}$	—	0.26	0.50	V	
Magnitude of Difference in V_{BE}	Q_1 & Q_2 Matched	—	0.5	5	mV	
Magnitude of Difference in I_B	$V_{CE} = 6\ \text{V}, I_C = 1\ \text{mA}$	—	0.2	3	μA	

*When used as a zener for reference voltage, the device must not be subjected to more than 0.1 millijoule of energy from any possible capacitance or electrostatic discharge in order to prevent degradation of the junction. Maximum operating zener current should be less than 10 mA.

DYNAMIC CHARACTERISTICS at $T_A = 25^\circ\text{C}$

CHARACTERISTICS	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
I/F Noise Figure	$f = 100\ \text{kHz}, R_S = 500\ \Omega, I_C = 1\ \text{mA}$	—	1.8	—	dB
Gain-Bandwidth Product	$V_{CE} = 6\ \text{V}, I_C = 5\ \text{mA}$	—	1.15	—	GHz
Collector-to-Base Capacitance	$V_{CB} = 6\ \text{V}, f = 1\ \text{MHz}$	—	See	—	pF
Collector-to-Substrate Capacitance	$V_{C1} = 6\ \text{V}, f = 1\ \text{MHz}$	—	Fig.	—	pF
Emitter-to-Base Capacitance	$V_{BE} = 4\ \text{V}, f = 1\ \text{MHz}$	—	5	—	pF
Voltage Gain	$V_{CE} = 6\ \text{V}, f = 10\ \text{MHz}$ $R_L = 1\ \text{k}\Omega, I_C = 1\ \text{mA}$	—	28	—	dB
Power Gain	Cascode Configuration $f = 100\ \text{MHz}, V^+ = 12\ \text{V}$	27	30	—	dB
Noise Figure	$I_C = 1\ \text{mA}$	—	3.5	—	dB
Input Resistance	Common-Emitter	—	400	—	Ω
Output Resistance	Configuration	—	4.6	—	$\text{k}\Omega$
Input Capacitance	$V_{CE} = 6\ \text{V}$	—	3.7	—	pF
Output Capacitance	$I_C = 1\ \text{mA}$	—	2	—	pF
Magnitude of Forward Transadmittance	$f = 200\ \text{MHz}$	—	24	—	mmho

Linear Integrated Circuits

CA3127E

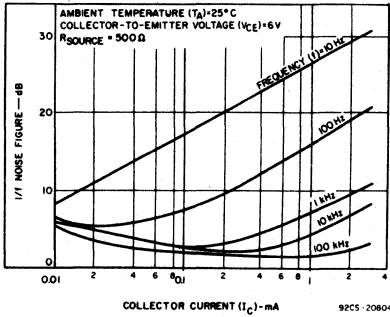


Fig. 2 - 1/f noise figure as a function of collector current at $R_{SOURCE} = 500 \Omega$.

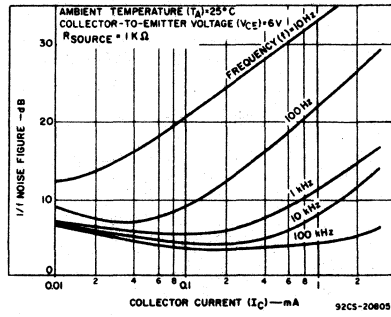


Fig. 3 - 1/f noise figure as a function of collector current at $R_{SOURCE} = 1 k\Omega$.

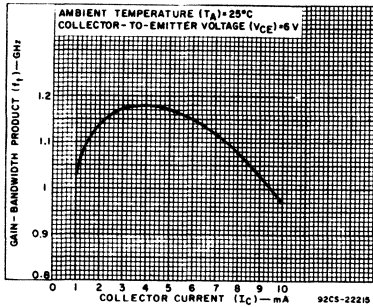


Fig. 4 - Gain-bandwidth product as a function of collector current.

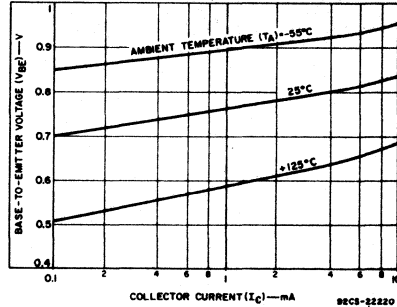


Fig. 5 - Base-to-emitter voltage as a function of collector current.

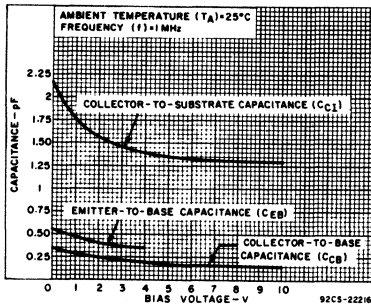


Fig. 6(a) - Capacitance as a function of bias voltage for Q_2 .

Transistor	Capacitance (pF)							
	C_{CB}		C_{CE}		C_{EB}		C_{CI}	
	Pkg.	Total	Pkg.	Total	Pkg.	Total	Pkg.	Total
Bias Voltage	-	6 V	-	6 V	-	4 V	-	6 V
Q1	0.025	0.190	0.090	0.125	0.365	0.610	0.475	1.65
Q2	0.015	0.170	0.225	0.265	0.130	0.360	0.085	1.35
Q3	0.040	0.200	0.215	0.240	0.360	0.625	0.210	1.40
Q4	0.040	0.190	0.225	0.270	0.365	0.610	0.085	1.25
Q5	0.010	0.165	0.095	0.115	0.140	0.395	0.090	1.35

Fig. 6(b) - Typical capacitance values at $f = 1 \text{ MHz}$. Three terminal measurement. Guard all terminals except those under test.

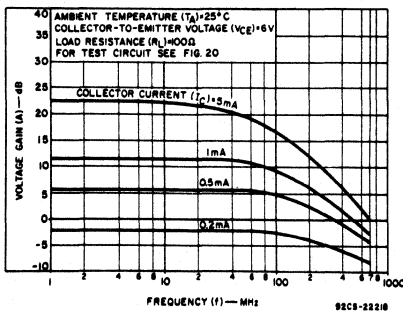


Fig. 7 - Voltage gain as a function of frequency at $R_L = 100 \Omega$.

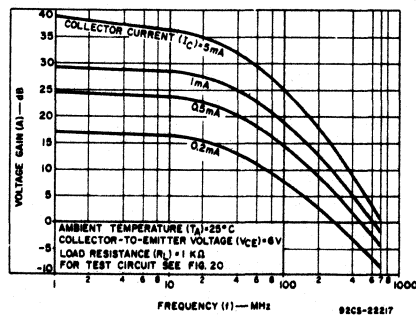


Fig. 8 - Voltage gain as a function of frequency at $R_L = 1 k\Omega$.

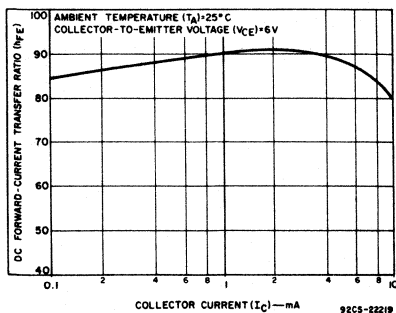


Fig. 9 - DC forward-current transfer ratio as a function of collector current.

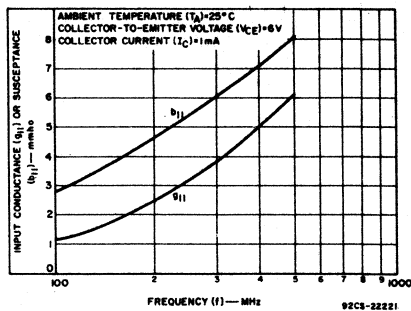


Fig. 10 - Input admittance (Y_{11}) as a function of frequency.

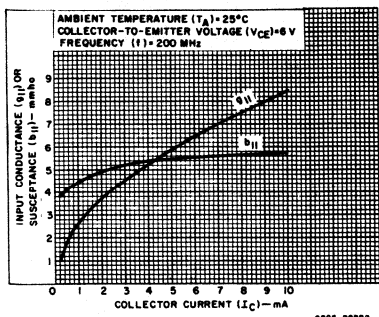


Fig. 11 - Input admittance (Y_{11}) as a function of collector current.

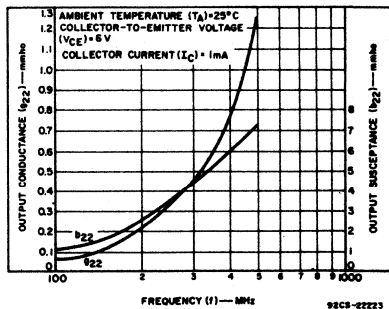


Fig. 12 - Output admittance (Y_{22}) as a function of frequency.

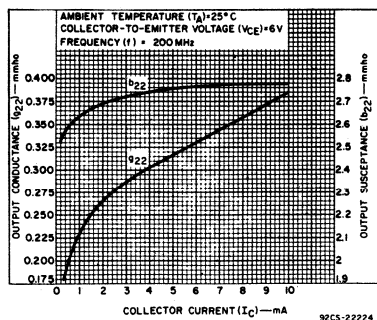


Fig. 13 - Output admittance (Y_{22}) as a function of collector current.

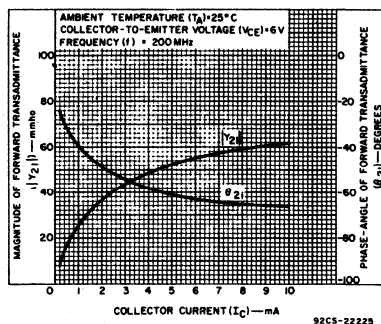


Fig. 14 - Forward transmittance (Y_{21}) as a function of collector current.

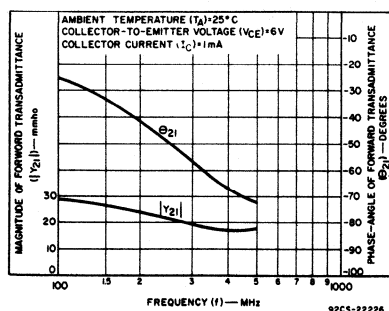


Fig. 15 - Forward transmittance (Y_{21}) as a function of frequency.

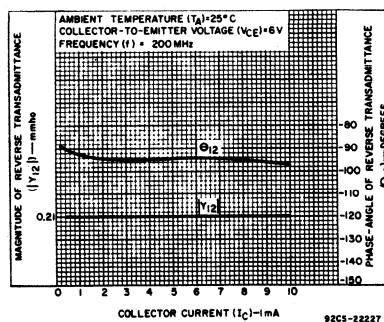


Fig. 16 - Reverse transmittance (Y_{12}) as a function of collector current.

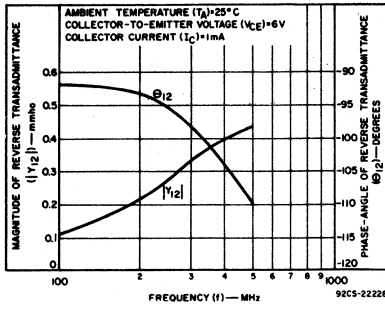


Fig. 17 - Reverse transmittance (Y_{12}) as a function of frequency.

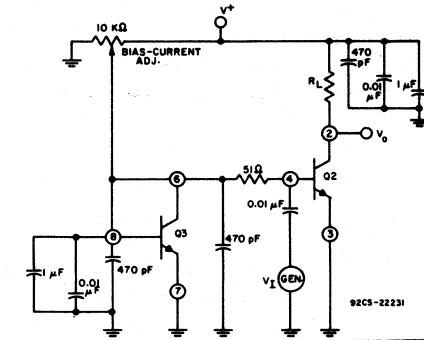


Fig. 18 - Voltage-gain test circuit using current-mirror biasing for Q_2 .

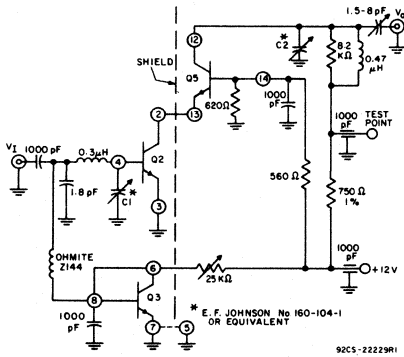


Fig. 19 - 100-MHz power-gain and noise-figure test circuit.

This circuit was chosen because it conveniently represents a close approximation in performance to a properly unilateralized single transistor of this type. The use of Q_3 in a current-mirror configuration facilitates simplified biasing. The use of the cascode circuit in no way implies that the transistors cannot be used individually.

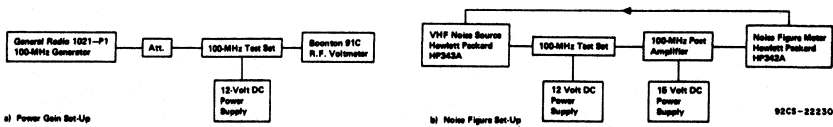
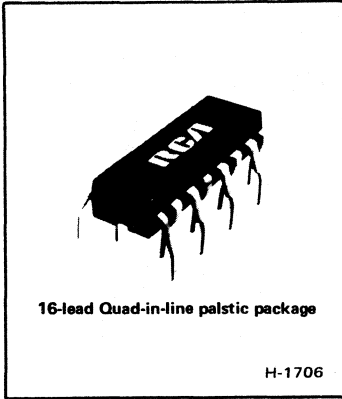


Fig. 20 - Block diagrams of power-gain and noise-figure test set-ups.

CA3128Q

TV Chroma Processor for PAL Systems



16-lead Quad-in-line plastic package

H-1706

Features:

- Phase-locked subcarrier regeneration utilizes sample-and-hold techniques in the automatic frequency phase control [AFPC] servo loop
- Automatic chrominance control [ACC]/killer detector employs sample-and-hold techniques
- Supplementary ACC with an overload detector to prevent oversaturation of the picture tube
- Sinusoidal subcarrier output
- Keyed chroma output
- Emitter-follower buffered outputs for low output impedance
- Linear dc saturation control
- PAL identification output
- Only the initial crystal filter tuning is required . . . no killer and ACC adjustments required at any time
- Few external components required
- Compensation for temperature and supply variations
- All terminals protected against short circuits

The RCA-CA3128Q is a monolithic silicon integrated circuit designed primarily for PAL chroma processing applications in color TV receivers. For a circuit description of the

CA3128Q and an explanation of this device in PAL systems, refer to "A New Chroma Processing IC Using Sample-and-Hold Techniques" by L.A. Harwood (ST6144).

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ C$

DC SUPPLY VOLTAGE (Between Terms. 12 and 15)	13.2 V
DC VOLTAGE (Term. 9):	
Positive Value	+3 V
Negative Value	-5 V
DEVICE DISSIPATION:	
Up to $T_A = 55^\circ C$	750 mW
Above $T_A = 55^\circ C$	derate linearly at 7.9 mW/ $^\circ C$
AMBIENT TEMPERATURE RANGE:	
Operating	-40 to +85 $^\circ C$
Storage	-65 to +150 $^\circ C$
LEAD TEMPERATURE (DURING SOLDERING):	
At a distance not less than 1/32" (0.79 mm) from case for 10 seconds max.	+265 $^\circ C$

TYPICAL STATIC CHARACTERISTICS at $T_A = 25^\circ C$:

DC Supply Current (I_{12}) with $V_{12} = 11.2 V$ dc	25 mA
--	-------

TYPICAL DYNAMIC CHARACTERISTICS at $T_A = 25^\circ C$ with a Burst-to-Chroma Ratio of 46.5%:

100% Chroma Output Voltage at $V_{I(p-p)} = 0.5 V$	3.5 V_{p-p}
Oscillator-Level Output Voltage	1 V_{p-p}
Killer Threshold Input Voltage	0.018 V_{p-p}
Pull-in Frequency	500 Hz
PAL Identification Output Voltage	1 V_{p-p}

Linear Integrated Circuits

CA3128Q

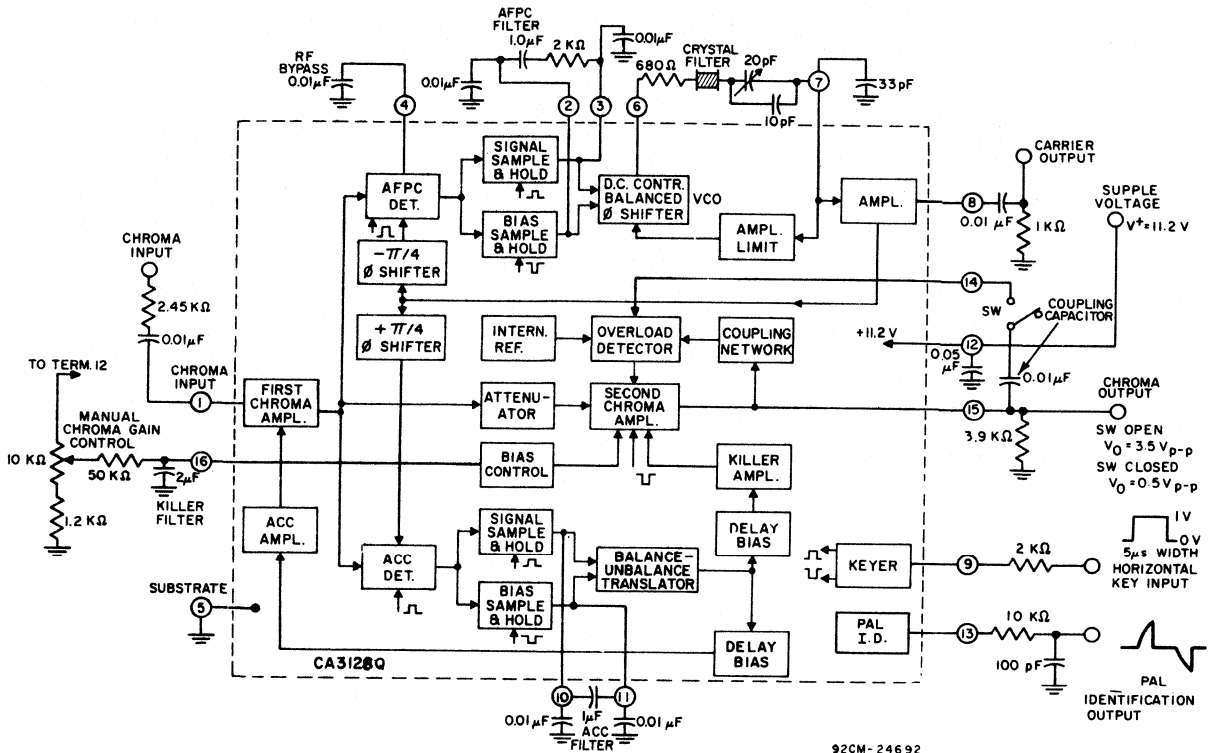
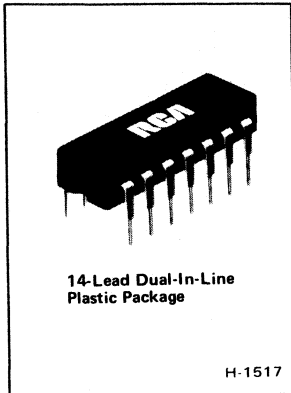


Fig. 1 - Block diagram of CA3128Q TV Chroma Processor.

CA3138E, CA3138AE

High-Current, High-Beta
N-P-N Transistor Arrays

For Industrial, Commercial, and Military Applications



Four Isolated Discrete Sealed-Junction High-Current N-P-N Transistors

Features:

- High Current –1 A
- High Beta – 95 min. at $I_C = 500$ mA, $V_{CE} = 5$ V
- Low $V_{CE(SAT)}$ –0.4 V max. at $I_C = 500$ mA, $I_B = 12.5$ mA
- Silicon Nitride Passivated
- Platinum Silicide Ohmic Contacts

The RCA-CA3138 and CA3138A are high-current n-p-n transistor arrays containing four isolated (discrete) sealed-junction high-current n-p-n transistors. They are intended for high-current, high-speed switching and driver applications.

The CA3138A has all the features and characteristics of the CA3138 but is intended for applications requiring premium grade specifications — higher rating for V_{CBO} of 25 volts and limits established for I_{CEO} , I_{EBO} , and h_{FE} at 10 mA.

The CA3138 and CA3138A are supplied in a 14-lead dual-in-line plastic package and operate over the full military temperature range of -55°C to $+125^{\circ}\text{C}$.

Applications:

- High-Current LED Driver
- Relay and Solenoid Driver
- Lamp Driver

MAXIMUM RATINGS, Absolute-Maximum Values:

COLLECTOR-TO-EMITTER VOLTAGE	15	V
With Base Open (V_{CEO})		
COLLECTOR-TO-BASE VOLTAGE		
With Emitter Open (V_{CBO})		
CA3138	20	V
CA3138A	25	V
EMITTER-TO-BASE VOLTAGE	5	V
With Collector Open (V_{EBO})		
COLLECTOR CURRENT (I_C)	1	A
POWER DISSIPATION (P_D):		
At T_A up to 25°C :		
For Each Transistor	1	W
Total Package	2	W
At T_A above 25°C derate linearly	20	mW/ $^{\circ}\text{C}$
AMBIENT TEMPERATURE RANGE:		
Operating	-55 to $+125$	$^{\circ}\text{C}$
Storage	-65 to $+150$	$^{\circ}\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):		
At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10 seconds max.	265	$^{\circ}\text{C}$

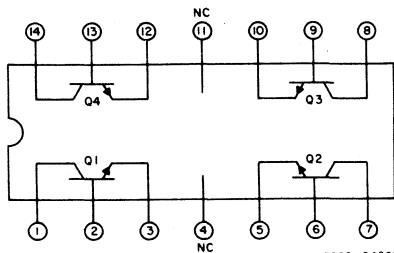


Fig. 1 — Terminal diagram (top view).

Linear Integrated Circuits

CA3138E, CA3138AE

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

Characteristic	Test Conditions	LIMITS						Units
		CA3138			CA3138A			
		Min.	Typ.	Max.	Min.	Typ.	Max.	
Collector-to-Emitter Sustaining Voltage, $V_{CEO(sus)}^*$	$I_C = 1\text{ mA}, I_B = 0$	15	20	—	15	20	—	V
Collector-to-Emitter Breakdown Voltage, $V_{(BR)CES}$	$I_C = 10\ \mu\text{A}$	20	55	—	25	60	—	V
Collector-to-Base Breakdown Voltage, $V_{(BR)CBO}$	$I_C = 10\ \mu\text{A}, I_E = 0$	20	55	—	25	60	—	V
Emitter-to-Base Breakdown Voltage, $V_{(BR)EBO}$	$I_E = 10\ \mu\text{A}, I_C = 0$	5	7.2	—	5	7.2	—	V
Base-to-Emitter Saturation Voltage, $V_{BE(sat)}^*$	$I_C = 500\text{ mA}, I_B = 12.5\text{ mA}$	0.7	0.81	1.1	0.7	0.81	1.1	V
Collector-to-Emitter Saturation Voltage, $V_{CE(sat)}^*$	$I_C = 500\text{ mA}, I_B = 12.5\text{ mA}$	—	0.26	0.4	—	0.26	0.4	V
Collector-Cutoff Current	I_{CBO} $V_{CB} = 15\text{ V}$	—	0.03	1	—	0.02	0.1	μA
	I_{CEO} $V_{CE} = 10\text{ V}$	—	0.5	—	—	0.3	1.0	
	I_{EBO} $V_{EB} = 4\text{ V}$	—	0.01	—	—	0.01	0.1	
Static Forward-Current Transfer Ratio (Beta), h_{FE}^*	$I_C = 10\text{ mA}, V_{CE} = 5\text{ V}$	—	—	—	35	140	—	
	$I_C = 100\text{ mA}, V_{CE} = 5\text{ V}$	80	160	450	80	160	450	
	$I_C = 500\text{ mA}, V_{CE} = 5\text{ V}$	95	170	500	95	170	500	
	$I_C = 1\text{ A}, V_{CE} = 5\text{ V}$	40	170	—	40	170	—	
Small-Signal Forward Current Transfer Ratio, h_{fe}	$I_C = 50\text{ mA}, V_{CE} = 10\text{ V}, f = 100\text{ MHz}$	2	—	—	2	—	—	
Collector-to-Base Capacitance, C_{CB}	$V_{CB} = 10\text{ V}, I_E = 0$	—	18	—	—	18	—	pF
Emitter-to-Base Capacitance, C_{EB}	$V_{EB} = 0.5\text{ V}, I_C = 0$	—	77	—	—	77	—	pF
Rise Time (See Test Ckt. Fig. 6), t_r	$I_C = 570\text{ mA}$	—	6	—	—	6	—	ns
Fall Time (See Test Ckt. Fig. 6), t_f	$I_{B1} = 30\text{ mA}$	—	100	—	—	100	—	ns
Delay Time (See Test Ckt. Fig. 6), t_d	$I_{B2} = 0$	—	7.5	—	—	7.5	—	ns
Storage Time (See Test Ckt. Fig. 6), t_s		—	850	—	—	850	—	ns

*Pulse Conditions: width = 300 μs ; duty cycle = 1%.

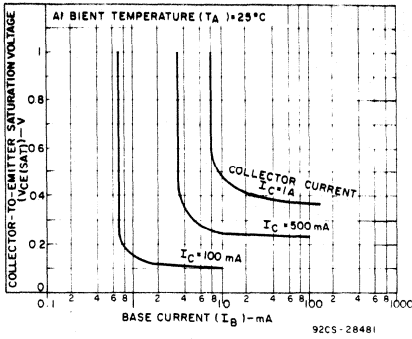


Fig. 2 - $V_{CE(sat)}$ vs I_B

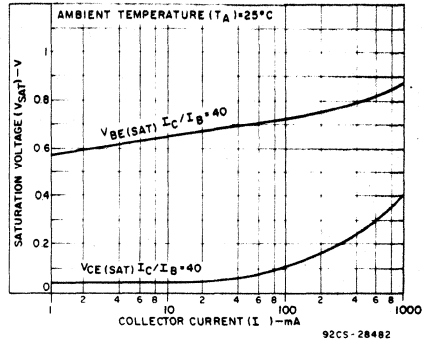


Fig. 3 - V_{sat} vs I_C

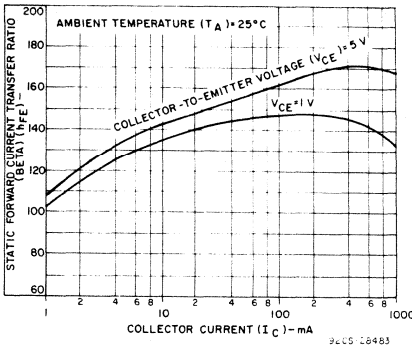


Fig. 4 - h_{FE} vs I_C

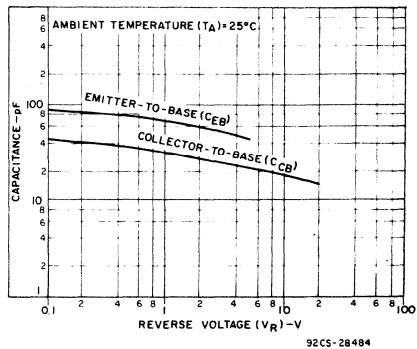


Fig. 5 - C_{CB}, C_{CE} vs V_R

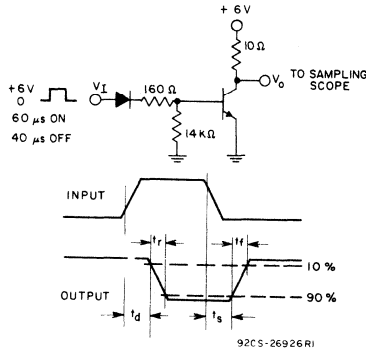
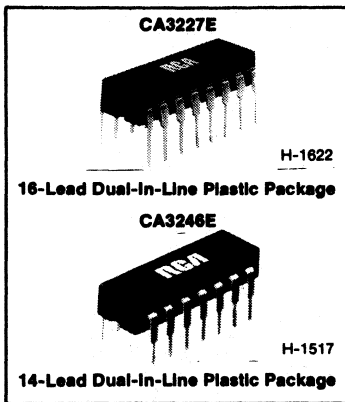


Fig. 6 - Switching time test circuit and waveforms.

Linear Integrated Circuits

CA3227E, CA3246E



High-Frequency N-P-N Transistor Arrays

For Low-Power Applications at Frequencies up to 1.5 GHz

Features:

- Gain-bandwidth product (f_T) > 3 GHz
- Five transistors on a common substrate

Applications:

- VHF amplifiers
- VHF mixers
- Multifunction combinations - RF/mixer/oscillator
- IF converter
- IF amplifiers
- Sense amplifiers
- Synthesizers
- Synchronous detectors
- Cascade amplifiers

The RCA-CA3227E and CA3246E* consist of five general-purpose silicon n-p-n transistors on a common monolithic substrate. Each of the transistors exhibits a value of f_T in excess of 3 GHz, making them useful from dc to 1.5 GHz. The monolithic construction of these devices provides close electrical and thermal matching of the five transistors.

The CA3227E is supplied in a 16-lead dual-in-line plastic package and the CA3246E is supplied in a 14-lead dual-in-line plastic package.

*Formerly RCA Developmental Nos. TA10854 and TA10855, respectively.

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A=25^\circ\text{C}$:

POWER DISSIPATION, P_D :

Any one transistor	85 mW
Total Package:	
For T_A up to 75°C	425 mW
For $T_A > 75^\circ\text{C}$ Derate Linearly at	6.67 mW/ $^\circ\text{C}$

AMBIENT TEMPERATURE RANGE:

Operating	-55 to $+125^\circ\text{C}$
Storage	-65 to $+150^\circ\text{C}$

LEAD TEMPERATURE (DURING SOLDERING):

At distance $1/16 \pm 1/32$ in. (1.59 ± 0.79 mm) from case for 10 seconds max.	$+265^\circ\text{C}$
--	----------------------

The following ratings apply for each transistor in the device.

Collector-to-Emitter Voltage, V_{CE0}	8 V
Collector-to-Base Voltage, V_{CB0}	12 V
Collector-to-Substrate Voltage, V_{C10}^{\S}	20 V
Collector Current, I_C	20 mA

^{\S}The collector of each transistor of these devices is isolated from the substrate by an integral diode. The substrate (terminal 5/CA3227E and terminal 13/CA3246E) must be connected to the most negative point in the external circuit to maintain isolation between transistors and to provide for normal transistor action.

CA3227E, CA3246E

STATIC ELECTRICAL CHARACTERISTICS at $T_A=25^\circ\text{C}$

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	LIMITS			UNITS
			Min.	Typ.	Max.	
For Each Transistor:						
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\ \mu\text{A}, I_E=0$	12	20	—	V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1\ \text{mA}, I_B=0$	8	10	—	V
Collector-to-Substrate Breakdown Voltage	$V_{(BR)C10}$	$I_{C1}=10\ \mu\text{A}, I_B=0, I_E=0$	20	—	—	V
Emitter-Cutoff-Current*	I_{EBO}	$V_{EB}=4.5\ \text{V}, I_C=0$	—	—	10	μA
Collector-Cutoff-Current	I_{CEO}	$V_{CE}=5\ \text{V}, I_B=0$	—	—	1	μA
Collector-Cutoff-Current	I_{CBO}	$V_{CB}=8\ \text{V}, I_E=0$	—	—	100	nA
DC Forward-Current Transfer Ratio	h_{FE}	$V_{CE}=6\ \text{V}$	$I_C=10\ \text{mA}$	—	110	—
			$I_C=1\ \text{mA}$	40	150	—
			$I_C=0.1\ \text{mA}$	—	150	—
Base-to-Emitter Voltage	V_{BE}	$V_{CE}=6\ \text{V}, I_C=1\ \text{mA}$	0.62	0.71	0.82	V
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=10\ \text{mA}, I_B=1\ \text{mA}$	—	0.13	0.50	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=10\ \text{mA}, I_B=1\ \text{mA}$	0.74	—	0.94	V

*On small-geometry, high-frequency transistors, it is very good practice never to take the Emitter Base Junction into reverse breakdown. To do so may permanently degrade the h_{FE} . Hence, the use of I_{EBO} rather than $V_{(BR)EBO}$. These devices are also susceptible to damage by electrostatic discharge and transients in the circuits in which they are used. Moreover, CMOS handling procedures should be employed.

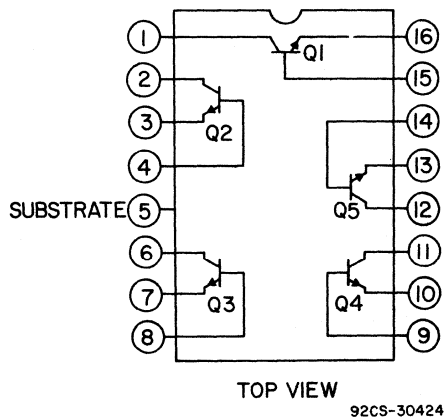


Fig. 1 - Schematic diagram of CA3227E.

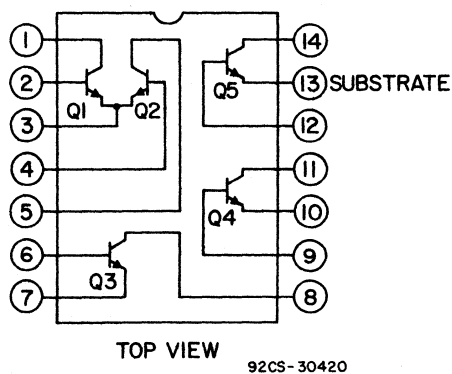


Fig. 2 - Schematic diagram of CA3246E.

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CA3227E, CA3246E

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A=25^\circ\text{C}$, 200 MHz, Common Emitter
Typical Values Intended Only for Design Guidance

CHARACTERISTIC	TEST CONDITIONS	TYPICAL VALUES	UNITS
For Each Transistor			
Input Admittance, Y_{11}	$\frac{b_{11}}{g_{11}}$	4	mmho
Output Admittance, Y_{22}	$\frac{b_{22}}{g_{22}}$	2.7	mmho
Forward Transfer Admittance, Y_{21}	$\frac{Y_{21}}{\theta_{21}}$	29.3	mmho
Reverse Transfer Admittance, Y_{12}	$\frac{Y_{12}}{\theta_{12}}$	0.38	mmho
Input Admittance, Y_{11}	$\frac{b_{11}}{g_{11}}$	4.8	mmho
Output Admittance, Y_{22}	$\frac{b_{22}}{g_{22}}$	2.75	mmho
Forward Transfer Admittance, Y_{21}	$\frac{Y_{21}}{\theta_{21}}$	95	mmho
Reverse Transfer Admittance, Y_{12}	$\frac{Y_{12}}{\theta_{12}}$	0.39	mmho
Small-Signal Forward Current Transfer Ratio	h_{21}	7.1	
		17	
Typical Capacities @ 1 MHz, Three-Terminal Measurement			
Collector-to-Base Capacitance, C_{CB}	$V_{CB}=6\text{ V}$	0.3	pF
Collector-to-Substrate Capacitance, C_{CI}	$V_{CI}=6\text{ V}$	1.6	pF
Collector-to-Emitter Capacitance, C_{CE}	$V_{CE}=6\text{ V}$	0.4	pF
Emitter-to-Base Capacitance, C_{EB}	$V_{EB}=3\text{ V}$	0.75	pF

OPERATING AND HANDLING CONSIDERATIONS

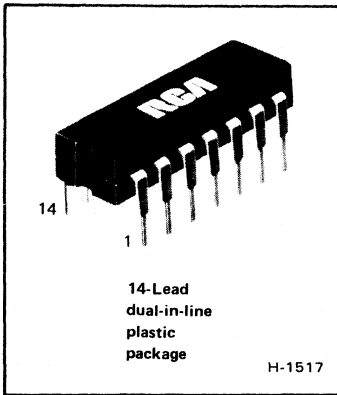
1. Handling

Recommended handling practices for CMOS devices are described in ICAN-6525 "Guide to Better Handling and Operation of CMOS Integrated Circuits."

2. Operating

Operating Voltage

During operation near the maximum supply voltage limit, care should be taken to avoid or suppress power supply turn-on and turn-off transients, power supply ripple, or ground noise; any of these conditions must not cause $V_{CC}-V_{EE}$ to exceed the absolute maximum rating.



COS/MOS Transistor Array

For Linear Circuit Applications

Applications:

- High input impedance, general-purpose amplifiers
- Pre-amplifiers
- Differential amplifiers
- Op-amps and comparators
- Constant-current sources and current mirrors
- Micropower amplifiers and oscillators
- Control of lamps, LED's, relays, and thyristors
- Timers
- Choppers
- Mixers

RCA-CA3600E is an array of Complementary-Symmetry MOS Field-Effect Transistors* on a monolithic silicon substrate. It is comprised of three n-channel and three p-channel enhancement-type MOS transistors arrayed as shown in Fig. 1, and specified and tested for linear circuit operation. These transistors are uniquely suitable for service in complementary-symmetry circuits at supply voltages in the range of 3 to 15 volts and are useful at frequencies up to 5 MHz (untuned). Each transistor in the CA3600E can conduct currents up to 10 mA. This device is supplied in the 14-lead dual-in-line plastic package.

Formerly RCA Dev. No. TA6368.

* The theory and construction of COS/MOS transistors are described in the "RCA COS/MOS Integrated Circuits Manual," RCA Solid State Division Technical Series Publication No. CMS-271.

Features:

- High input resistance 100 GΩ (typ.)
- Low gate-terminal current 10 pA (typ.)
- Matched p-channel pair:
Gate-voltage differential ($I_D = -100 \mu A$) ± 20 mV (max.)
- No "Popcorn" (burst) noise
- Stable transfer characteristics over an operating temperature range of $-55^\circ C$ to $+125^\circ C$ when operated in complementary circuit configuration at supply voltages in the 5 to 15 volt range (see Fig. 14)
- Integrated integral gate-protection system (see Fig. 34)
- High voltage gain (see Fig. 11). . . up to 53 dB (typ.) per COS/MOS stage
- Individual MOS transistors have square-law characteristics, superior cross-modulation performance, and greater dynamic range than bipolar transistors

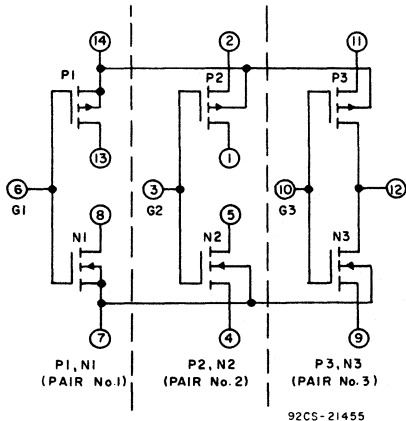


Fig. 1 — Schematic diagram for CA3600E COS/MOS transistor array. (See Fig. 34 for internal gate-and-channel-protection circuits)

1. Drain terminal, p-channel of pair no. 2
2. Source terminal, p-channel of pair no. 2
3. Common gate terminal of pair no. 2
4. Source terminal, n-channel of pair no. 2
5. Drain terminal, n-channel of pair no. 2
6. Common gate terminal of pair no. 1
7. Source terminal, n-channel of pair no. 1 and substrate connection for all n-channel transistors - - - V_{SS} terminal
8. Drain terminal, n-channel of pair no. 1
9. Source terminal, n-channel of pair no. 3
10. Common gate terminal of pair no. 3
11. Source terminal, p-channel of pair no. 3
12. Common drain terminal of pair no. 3
13. Drain terminal, p-channel of pair no. 1
14. Source terminal, p-channel of pair no. 1 and substrate connection for all p-channel transistors - - - V_{DD} terminal

Terminal Identification for Fig. 1.

Linear Integrated Circuits

CA3600E

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

DISSIPATION:

Any one transistor at T_A up to 55°C	150 mW
Total package at T_A up to 55°C	750 mW
Above $T_A = 55^\circ\text{C}$	derate linearly 6.67 mW/ $^\circ\text{C}$

AMBIENT TEMPERATURE RANGE:

Operating	-55 to $+125^\circ\text{C}$
Storage	-65 to $+150^\circ\text{C}$

LEAD TEMPERATURE (During Soldering)

At distance not less than $1/16'' \pm 1/32''$ (1.59 ± 0.79 mm) from case for 10 s max.	265°C
--	---------------------

The Following Ratings Apply for Each Transistor in the Device:

DRAIN-TO-SOURCE VOLTAGE, V_{DS} :

n-channel	+15 V
p-channel	-15 V

DRAIN-TO-GATE VOLTAGE, V_{DG} :

n-channel	+15 V
p-channel	-15 V

SOURCE-TO-SUBSTRATE VOLTAGE, V_{SB} :

n-channel	+15 V
p-channel	-15 V

GATE-TO-SOURCE VOLTAGE, V_{GS} :

p-channel transistors (p_1, p_2, p_3).	0 V (min.), $-V_D$ (max.)
n-channel transistors (n_1, n_2, n_3).	0 V (min.), $+V_D$ (max.)
COS/MOS transistor-pairs ($p_1-n_1, p_2-n_2, p_3-n_3$).	0 V (min.), $+V_{DD}$ (max.)

DRAIN CURRENT, $ I_D $	10 mA
----------------------------------	-------

GATE CURRENT, $ I_G $	100 μA
---------------------------------	-------------------

The Following Rating Applies for Each COS/MOS Transistor-Pair in the Device:

DC SUPPLY VOLTAGE ($V_{DD} - V_{SS}$)	+15 V
---	-------

Rules for Maintaining Electrical Isolation Between Transistors and Monolithic Substrate

Terminal No. 14 must be maintained at the most positive potential (or equally positive potential) with respect to any other terminal in the CA3600E.

Terminal No. 7 must be maintained at the most negative potential (or equally negative potential) with respect to any other terminal in the CA3600E.

Violation of these rules will result in improper transistor operation, circuit "latching," and/or possible permanent damage to the CA3600E.

Note: Users should observe the "Considerations in Handling CA3600E Devices", discussed on page 13.

ELECTRICAL CHARACTERISTICS, At $T_A = 25^{\circ}C$

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	TYPICAL CURVE OR CIRCUIT FIG. NO.	LIMITS			UNIT
				Min.	Typ.	Max.	
For Each p-Channel MOS Transistor							
Drain Current	I_D	$V_{DS} = -10\text{ V}, V_{GS} = -3.6\text{ V}$	2,3,4	-0.5	-1.1	-2.0	mA
Gate-to-Source Threshold Voltage	$V_{GS(th)}$	$I_D = -10\text{ }\mu\text{A}$	-	-	-1.75	-	V
Gate-to-Source Voltage Differential (p_1 vs. p_2)	$ V_{GS1} - V_{GS2} $	$I_D = -100\text{ }\mu\text{A}, V_{DS} = -10\text{ V}$	5	-	± 4	± 20	mV
Forward Transconductance	g_{fs}	$I_D = -1\text{ mA}, f = 1\text{ kHz}$	6	-	920	-	μmho
Low-Frequency Noise Voltage	e_N	$I_D = -1\text{ mA}, f = 1\text{ kHz}, R_s = 0\text{ }\Omega$	7	-	0.03	-	$\mu\text{V } \sqrt{\text{Hz}}$
Low-Frequency Noise Current	i_N	$I_D = -1\text{ mA}, f = 1\text{ kHz}, R_s = 1\text{ M}\Omega$	7	-	0.2	-	$\text{pA } \sqrt{\text{Hz}}$
Current-Mirror Transfer Ratio (p_1/p_2)	I_{MTR}	$I_1 = -100\text{ }\mu\text{A}, V_{DS} = -10\text{ V}$	30	0.7	1.1	1.5	-
Gate-Terminal Current	I_{GT}	$V_{DS} = -10\text{ V}, V_{GS} = -3.5\text{ V}$	-	-	± 0.015	-40	nA
Input Capacitance	C_I	-	-	-	6.3	-	pF
Output Capacitance	C_O	-	-	-	3	-	pF
Input-to-Output Capacitance	C_{I-O}	-	-	-	0.75	-	pF
For Each n-Channel MOS Transistor							
Drain Current	I_D	$V_{DS} = +10\text{ V}, V_{GS} = +3.6\text{ V}$	2,3,4	0.4	0.9	1.6	mA
Gate-to-Source Threshold Voltage	$V_{GS(th)}$	$I_D = 10\text{ }\mu\text{A}$	-	-	1.5	-	V
Gate-to-Source Voltage Differential (n_1 vs. n_2)	$ V_{GS1} - V_{GS2} $	$I_D = 100\text{ }\mu\text{A}, V_{DS} = +10\text{ V}$	5	-	± 30	-	mV
Forward Transconductance	g_{fs}	$I_D = 1\text{ mA}, f = 1\text{ kHz}$	6	-	860	-	μmho
Low-Frequency Noise Voltage	e_N	$I_D = 1\text{ mA}, f = 1\text{ kHz}, R_s = 0\text{ }\Omega$	7	-	0.2	-	$\mu\text{V } \sqrt{\text{Hz}}$
Low-Frequency Noise Current	i_N	$I_D = 1\text{ mA}, f = 1\text{ kHz}, R_s = 1\text{ M}\Omega$	7	-	0.3	-	$\text{pA } \sqrt{\text{Hz}}$
Current-Mirror Transfer Ratio (n_1/n_2)	I_{MTR}	$I_1 = 100\text{ }\mu\text{A}, V_{DS} = +10\text{ V}$	29	0.7	1.3	2.0	-
Gate-Terminal Current	I_{GT}	$V_{DS} = +10\text{ V}, V_{GS} = +3.7\text{ V}$	-	-	± 0.01	+40	nA
Input Capacitance	C_I	-	-	-	5.5	-	pF
Output Capacitance	C_O	-	-	-	2.0	-	pF
Input-to-Output Capacitance	C_{I-O}	-	-	-	0.35	-	pF
For Each COS/MOS Transistor Pair							
Drain Current	I_{DD}	$V_{DD} = +10\text{ V}$	9,10	1.0	2.2	4.0	mA
Drain-to-Source Cutoff Current	$I_{DD(off)}$	$V_{DD} = +10\text{ V}, V_{SS} = 0\text{ V}$ Gate Voltage(V_G) = +10 V or 0 V	8	-	0.5	100	nA
DC Output Voltage	V_O	$V_{DD} = +10\text{ V}$	10	4.2	5.0	5.8	V
Forward Transconductance	g_{fs}	$V_{DD} = +10\text{ V}, f = 1\text{ kHz}$	6	-	2300	-	μmho
Slew Rate (Open-Loop)	SR	$V_{DD} = +15\text{ V}$	10	-	95	-	$\text{V}/\mu\text{s}$
Amplifier Voltage Gain	A_{OL}	$V_{DD} = +10\text{ V}, f = 1\text{ kHz}, R_b = 22\text{ M}\Omega$ $R_s = 50\text{ }\Omega$	10,11	-	32	-	dB
Gate-Terminal Current	I_{GT}	$V_{DD} = +10\text{ V}$	10	-	± 0.005	± 20	nA
Broadband Output Noise Voltage	E_{ON}	$V_{DD} = +10\text{ V}, R_b = 22\text{ M}\Omega, R_s = 10\text{ k}\Omega$	10,11	-	500	-	μV
Input Capacitance	C_I	-	-	-	11.8	-	pF
Output Capacitance	C_O	-	-	-	5.0	-	pF
Input-to-Output Capacitance	C_{I-O}	-	-	-	1.1	-	pF

Linear Integrated Circuits

CA3600E

TYPICAL CHARACTERISTICS CURVES

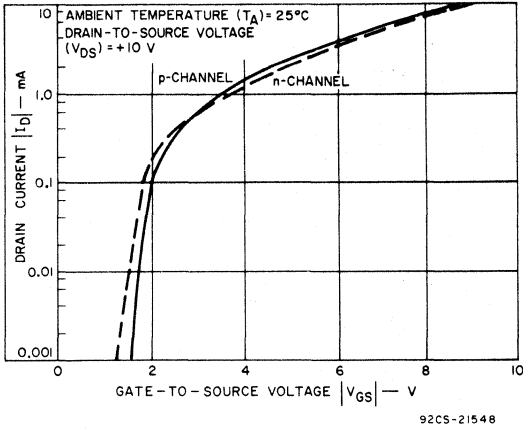


Fig. 2—Drain current vs. gate-to-source voltage.

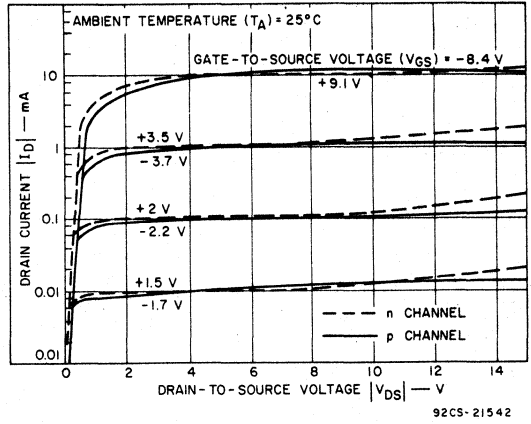


Fig. 3—Drain current vs. drain-to-source voltage.

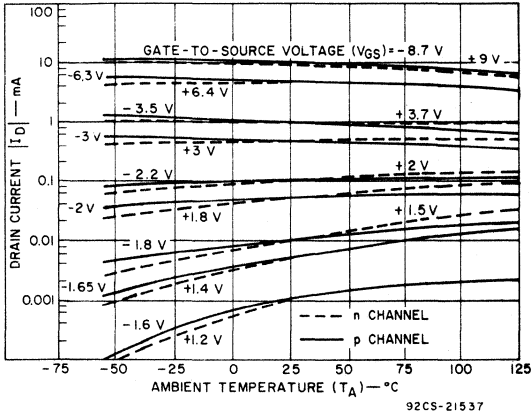


Fig. 4—Drain current vs. ambient temperature.

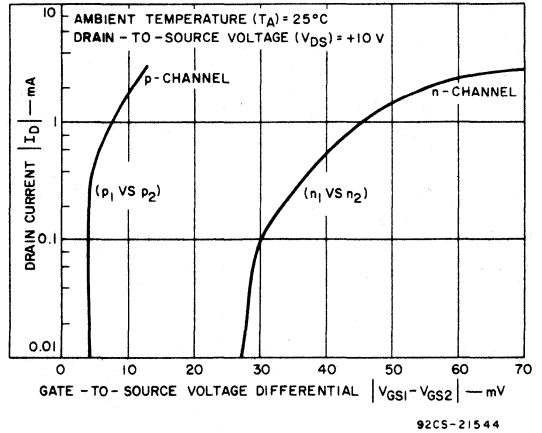


Fig. 5—Gate-to-source voltage differential vs. drain current.

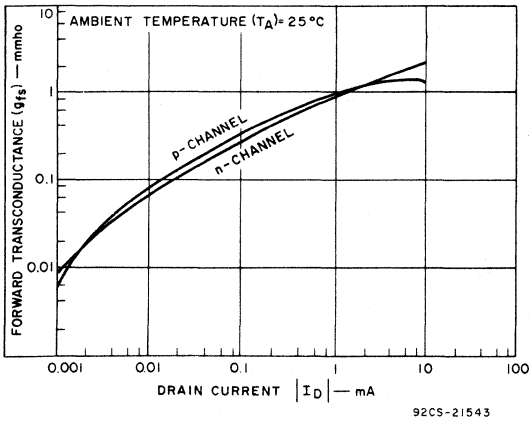


Fig. 6—Forward transconductance vs. drain current.

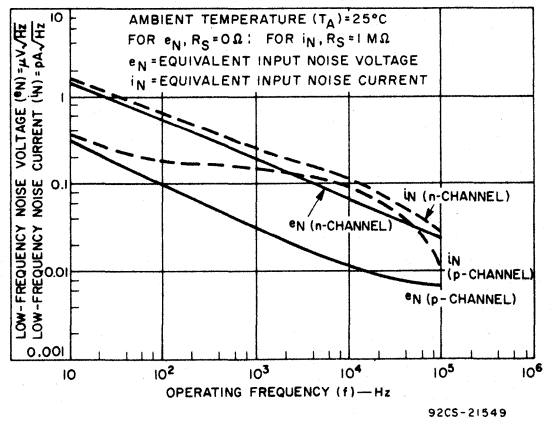


Fig. 7—Noise voltage and noise current vs. operating frequency.

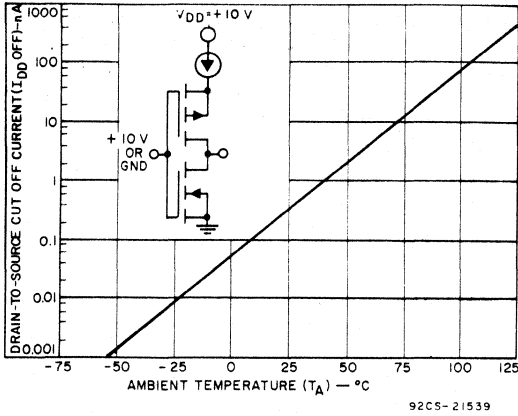


Fig. 8— Drain-to-source cutoff current vs. ambient temperature.

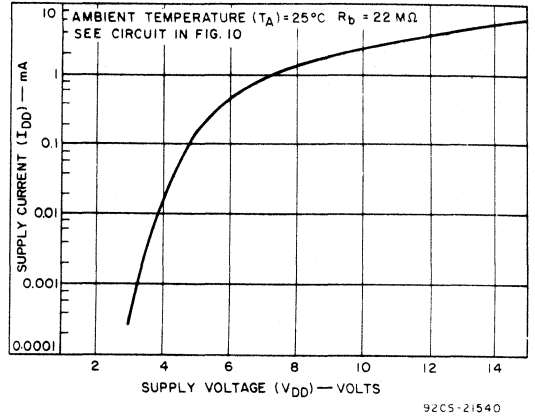


Fig. 9— Typical V_{DD} vs. I_{DD} characteristics for amplifier circuits of Fig. 10 and Fig. 15.

APPLICATIONS

The Basic COS/MOS Linear Amplifier

P-n-p and n-p-n bipolar transistors have been used for many years in the design of so-called "true-complementary" linear amplifier circuits¹. Since mutually compatible p-channel and n-channel MOS/FET devices were not generally available, "true-complementary" amplifier circuits using MOS transistors were seldom used. Now, COS/MOS transistor technology⁵ has made it possible to supply compatible p-channel/n-channel transistors in monolithic IC form such as the CA3600E COS/MOS transistor array shown in Fig. 1.

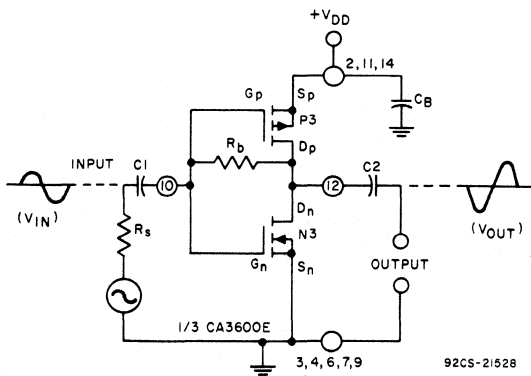


Fig. 10— COS/MOS transistor-pair biased for linear-mode operation.

A "True-Complementary" Linear Amplifier Using COS/MOS Transistors

Fig. 10 shows the schematic diagram of a single-stage "true-complementary" linear amplifier using one pair of the complementary MOS transistors in the CA3600E, connected in a common-source circuit. Resistor R_b is used to bias the complementary pair for Class A operation, as described subsequently, and R_s represents the source resistance of the

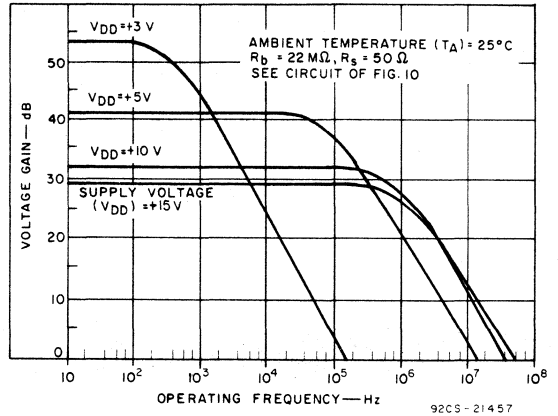


Fig. 11— Typical voltage gain vs. frequency characteristics for amplifier circuit of Fig. 10.

signal source. This generic amplifier is suitable for operation with a single or split voltage supply in the range of 3 to 15 volts. Fig. 11 shows voltage gain as a function of operating frequency at various supply voltages for the single-stage amplifier. This amplifier is capable of producing very high output-swing voltages (V_{OUT}); for example, its output voltages can be swung to within several millivolts of either supply-voltage "rail". Fig. 9 shows typical supply voltage (V_{DD}) vs. supply current (I_{DD}) characteristics for the single-stage amplifier. The curves in Fig. 12 show the normalized amplifier supply current as a function of ambient temperature at various supply voltages. When the amplifier is operating at $V_{DD} = 3$ V, the supply current changes rapidly as a function of temperature because the MOS transistors are operating in the proximity of their individual gate-source threshold voltages.

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CA3600E

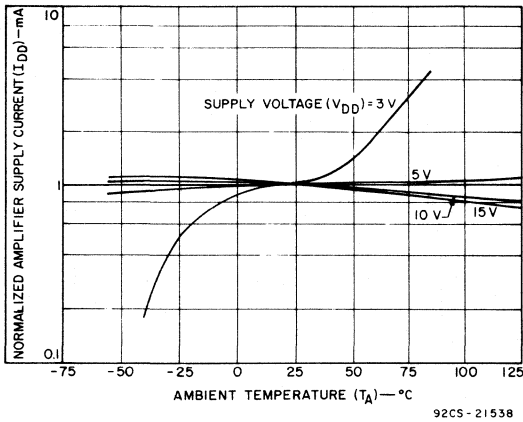


Fig. 12— Normalized amplifier supply current vs. ambient temperature characteristics for amplifier circuit of Fig. 10.

Voltage-Transfer Characteristics

Fig. 13 illustrates a voltage-transfer characteristic curve of a COS/MOS transistor pair connected in the amplifier circuit of Fig. 10, with a biasing resistor (R_b) connected between the drain and gate terminals (10,12). If the p- and n-channel transistors have identical characteristics, their channel resistances are equal, and the biasing method shown establishes a steady-

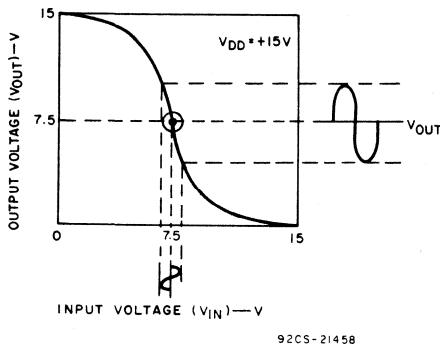


Fig. 13 — Representation of voltage-transfer characteristics for COS/MOS transistor pair.

state condition such that terminal 12 is at mid-potential between V_{DD} and ground. Thus, with negligibly small gate-source leakage resistances, under zero-signal conditions, the biasing resistor (R_b) establishes gate potential at the mid-point between V_{DD} and ground, i.e., $V_{in} = V_{out}$. Under these conditions the amplifier is biased for operation about the mid-point ("0") in the linear segment on the steep transition of the voltage-transfer characteristic as shown in Fig. 13. When the input signal (V_{in}) swings in the positive direction, there is a reduction in the instantaneous output voltage (V_{out}) with respect to ground. Negative-going input signals have inverse effects. Thus, phase-inversion occurs in the COS/MOS-pair amplifier. Power-supply current is constant during dynamic

linear operation, i.e., Class A amplifier service. When the signal input-voltage level (V_{in}) becomes very large, the output signal (V_{out}) waveforms become distorted because the transistors are driven into the non-linear portions of their voltage-transfer characteristics. If the positive-going input-signal is sufficiently large, for example, the p-channel transistor can be driven to cutoff and the amplifier supply current (I_{DD}) is reduced to essentially zero.

Fig. 14 shows typical voltage-transfer characteristics of each COS/MOS pair in the CA3600E at several values of V_{DD} . The shape of these transfer characteristics is comparatively constant despite temperature changes from -55 to $+125^\circ C$.

The biasing arrangement used in the circuit of Fig. 10 provides an easy method of establishing feedback for ac signals in accordance with the R_b/R_s ratio. When the feedback of ac signals is not desirable, the circuit of Fig. 15 may be used. The ac bypass capacitor (C_3) minimizes ac signal feedback.

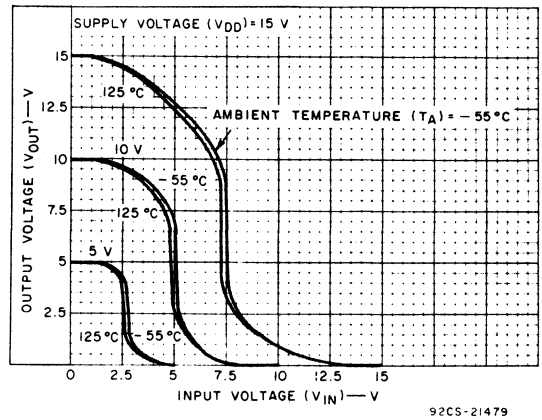


Fig. 14— Voltage transfer characteristics for COS/MOS transistor-pair amplifier in Fig. 10.

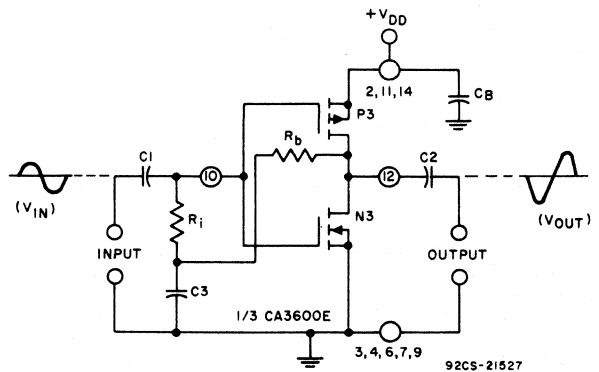


Fig. 15— Alternate method of biasing COS/MOS transistor-pair for linear-mode operation.

CA3600E

Cascading Amplifier Stages of COS/MOS Transistor Pairs

Ultra-high-gain amplifiers can be designed by cascading stages of COS/MOS transistor pairs as shown in Fig. 16. The biasing system used is similar to that described above in connection with Fig. 10. The supply current for the three-stage amplifier shown in Fig. 16 is typically three times the values shown in Fig. 9. Gain and frequency-response characteristics of the amplifier are shown in Fig. 17.

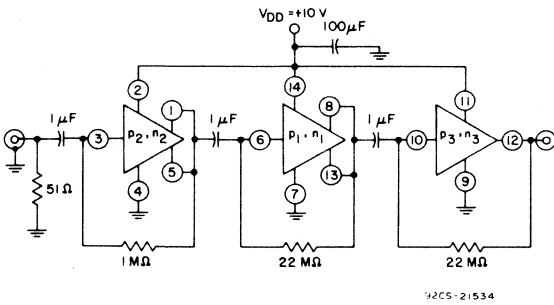


Fig. 16— High-gain amplifier uses cascaded COS/MOS transistor-pair in CA3600E.

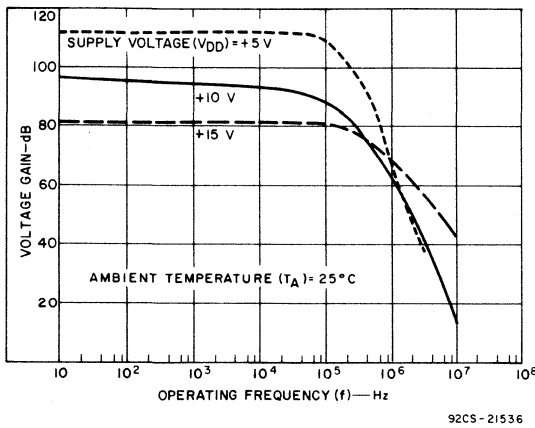


Fig. 17— Typical voltage gain vs. operating frequency characteristics for three-stage COS/MOS transistor-pair amplifier in Fig. 16.

Post-Amplifiers For Op-Amps

COS/MOS transistor-pairs can be advantageously applied as post-amplifiers for op-amps. Because the input impedance of the COS/MOS pair is comparatively high, the op-amp operates under essentially unloaded conditions. Each COS/MOS pair can sink and source output current up to about 10 mA. Additionally, the op-amp output can be directly coupled to bias the COS/MOS pair. A detailed description of the subject has been published previously.²

The schematic diagram in Fig. 18 shows a COS/MOS transistor-pair serving as a post-amplifier to an RCA-CA3080 Operational Transconductance Amplifier.³ The approximate 30-dB gain in

a single COS/MOS transistor-pair is an added increment to the 100-dB gain in the CA3080, yielding a total forward gain of about 130 dB. The open-loop slew rate of the circuit in Fig. 19 is approximately 65 V/µs. When compensated for the unity-gain voltage-follower mode shown in Fig. 19, the slew rate is about 1 V/µs. For greater current output, the two remaining transistor pairs of the CA3600E may be connected in parallel with the single stages shown in Figs. 18 and 19.

The use of the two-stage COS/MOS post-amplifier shown in Fig. 20 increases the total open-loop gain of the system to about 160 dB (100,000,000X). Open-loop slew rate remains at about 65 V/µs. A slew rate of about 1 V/µs is maintained with this circuit connected in the unity-gain voltage-follower mode, as shown in Fig. 21. These circuits operate in concert with stability.

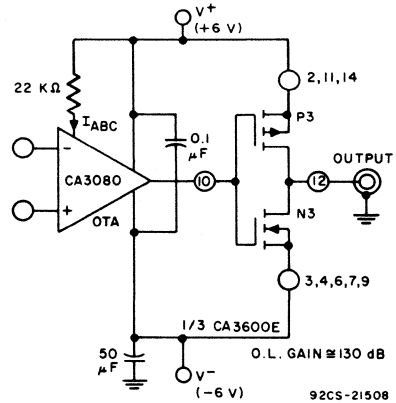


Fig. 18— COS/MOS transistor-pair used as post-amplifier to op-amp in open-loop circuit.

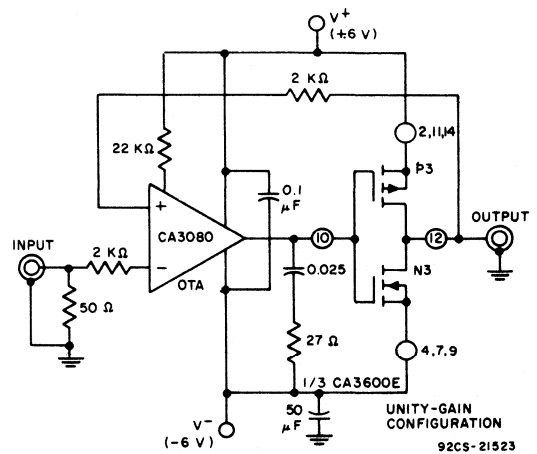


Fig. 19— COS/MOS transistor-pair used as post-amplifier to op-amp in unity-gain circuit.

CA3600E

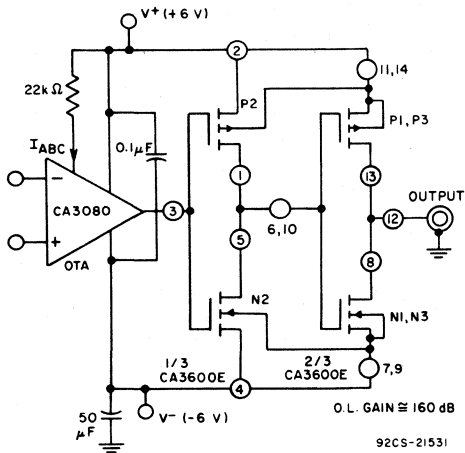


Fig. 20—COS/MOS transistor-pairs used as two-stage post-amplifier to op-amp in open-loop circuit.

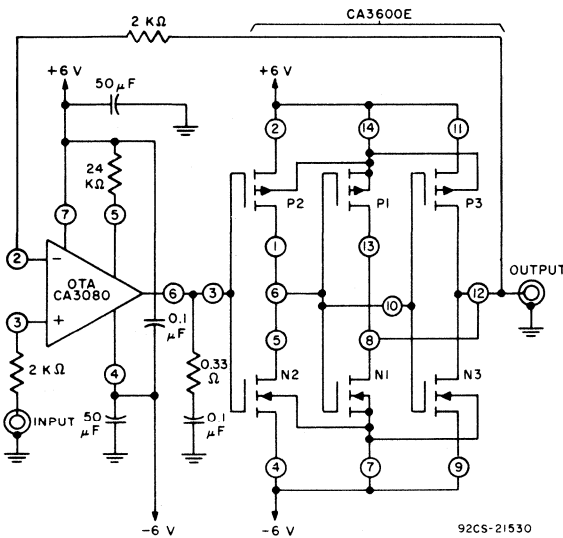


Fig. 21—Unity-gain amplifier uses COS/MOS transistor-pairs as two-stage post-amplifier to op-amp.

Multivibrators, Threshold Detectors, and Comparators

Descriptions of several circuits using COS/MOS transistor-pairs in both monostable and astable multivibrators have been published.^{4,5} The characteristics of COS/MOS pairs are also ideal for mating with micropower op-amps in circuits such as the precision multistable circuits shown in Fig. 22. In these circuits precise timing and thresholds are assured by the stable characteristics of the input differential amplifier in the CA3080 Operational Transconductance Amplifier.^{2,3} Moreover, speed vs. power consumption tradeoffs can be made by adjustment of the Amplifier-Bias-Current (I_{ABC}) supplied to terminal 5 of the CA3080. The quiescent power consumption of the circuits shown in Fig. 22 is typically 6 mW, but can be made to operate in the micropower region by suitable modifications.

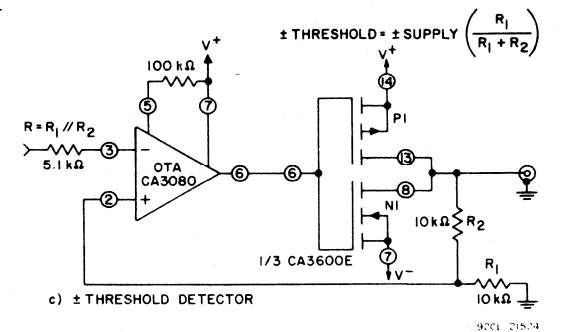
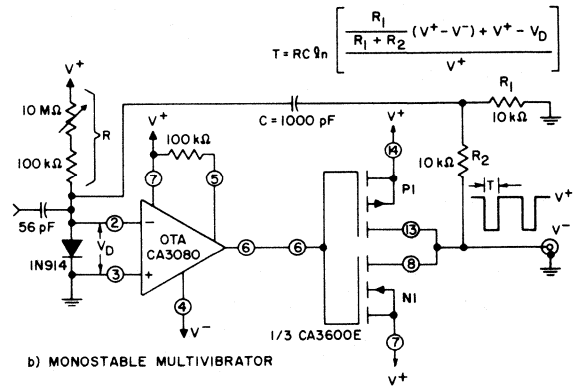
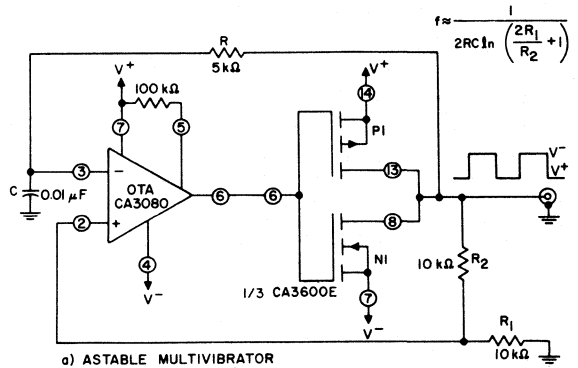


Fig. 22—Multistable circuits using COS/MOS transistor-pairs.

The schematic diagram of a programmable micropower comparator, shown in Fig. 23 employs the combination of an op-amp (CA3080A) and COS/MOS transistor-pairs in the CA3600E. Quiescent power consumption of the circuit is about 10 μ W (typ.). When the comparator is strobed "ON", transistor P1 is driven into conduction and the OTA becomes active. Under these conditions, the circuit consumes 420 μ W and responds to a differential-input signal in about 8 μ s. By suitably biasing the CA3080A, the circuit response time can be decreased to about 150 ns but the power consumption is increased to 21 mW. The differential amplifier input common-mode range for this circuit is -1 V to +10.5 V. Voltage gain of this micropower comparator is typically 130 dB.

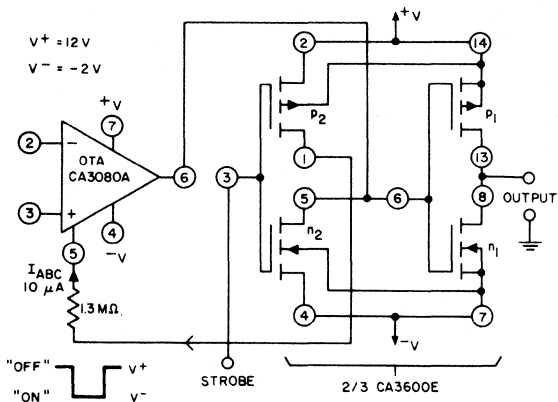


Fig. 23— Programmable micropower comparator.

Operational Amplifiers

COS/MOS transistor-pairs can be used in conjunction with a bipolar transistor-array IC to build an op-amp as shown in Fig. 24. It is particularly suited for single-supply operation (e.g., mobile and aircraft service). The op-amp is unique in that it is responsive to small-signal ground-referenced inputs and the output stage can easily be driven within 1 mV of ground potential. Its open-loop gain characteristics are shown in Fig. 25; the open-loop slew rate is approximately 30 V/μs.

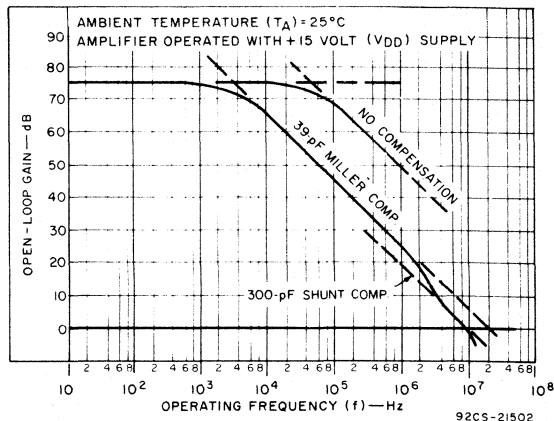


Fig. 25— Open-loop gain characteristic for op-amp in Fig. 24.

This circuit is ideal for use as a unity-gain voltage-follower and has been described for operation in connection with a 9-Bit Single-Supply Digital-to-Analog Converter (DAC) using COS/MOS transistors in the resistor-network switches.⁶

The op-amp in Fig. 24 has three stages; its first stage is a differential input circuit using two p-channel transistors (P₄,P₅) in a CA3600E. The second stage is an n-p-n

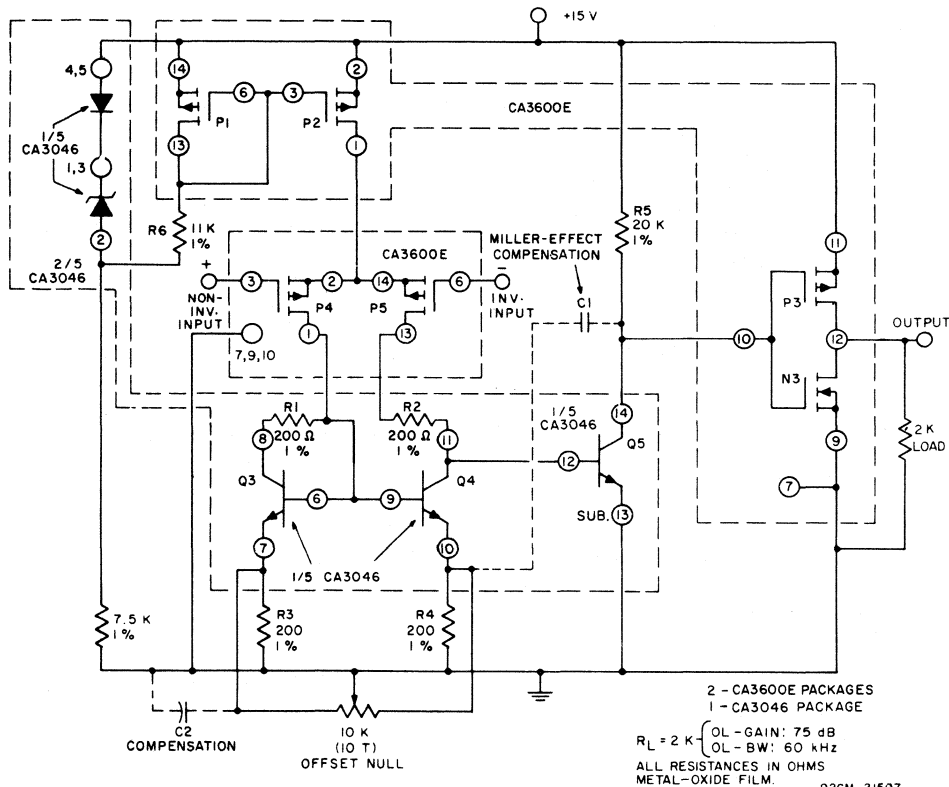


Fig. 24— Operational amplifier using COS/MOS transistor-pairs.

2 - CA3600E PACKAGES
1 - CA3046 PACKAGE
R_L = 2 K { OL - GAIN: 75 dB
 OL - BW: 60 kHz
ALL RESISTANCES IN OHMS
METAL-OXIDE FILM. 92CM-21507

CA3600E

transistor (Q_5) and the output stage is a COS/MOS transistor-pair (P_3, N_3) operating in the manner described above. A constant current of about $400 \mu\text{A}$ is established in the differential input stage by the zener network in the upper-left portion of Fig. 24. The zener network energizes a current mirror comprised of two p-channel transistors (P_1, P_2) to establish constant-current flow in the differential amplifier stage (P_4, P_5). The drain load for the differential amplifier consists of resistors R_1, R_4 and a current mirror (Q_3, Q_4) to optimize conditions for balanced operation of the differential amplifier. The operating theory of current-mirror circuits has been described in reference ². Amplifier voltage-offset is nulled with the 10-kilohm balance potentiometer. The second-stage current is established by R_5 , and is selected to approximate the first-stage current level ($400 \mu\text{A}$), to assure similar positive and negative slew rates. The amplifier is shown driving a 2-kilohm load, a typical value used with monolithic op-amps. Voltage gain varies inversely with the choice of load resistance.

The amplifier can be compensated with a single capacitor (C_1), connected as shown by the dotted lines. However, optimum compensation for the unity-gain non-inverting mode is provided by two capacitors: Miller Effect feedback through a 39-pF capacitor C_1 (connected as shown), and a 300-pF capacitor connected between terminals 7 and 13 of the CA3046 transistor array to shunt one-half the driving current. Fig. 25 shows the open-loop gain characteristics with compensation for unity-gain operation. When the amplifier is operated as a voltage-follower, it is recommended that a 1-kilohm resistor, shunted with a 150-pF capacitor, be connected between the amplifier output terminal and terminal 6 of P_5 to avoid a potential latch situation involving the integral gate-protection network. The circuit can also be latched if either input terminal is driven more than about 0.7 volt below ground potential. This latch situation can be avoided by connecting a 1N914 diode from each input terminal to ground, with the diode anode grounded.

Analog Timer

The CA3600E is useful in the design of analog timer circuits. A typical circuit is shown in Fig. 26. For purposes of explanation, let it be assumed that capacitor C_1 initially is in a completely discharged condition; terminal 10, therefore, is initially at ground potential and transistor N_3 is non-conductive. The circuitry at the left of terminal 10 provides a source of constant-current flow through P_1 to charge capacitor C_1 increasingly positive with respect to ground. After the passage of time (T), capacitor C_1 is charged sufficiently in the positive direction so that transistor N_3 is driven into conduction by its gate and the lamp is lighted to signify the end of the time-delay period. The circuit is reset by momentarily closing switch S_1 to discharge capacitor C_1 through R_4 . Resistor-divider network R_1, R_2 establishes the supply voltage to a constant-current network comprised of resistor R_3 and the series-connected COS/MOS pair N_2, P_2 , biased for linear operation by resistor R_5 as previously described. This combination is connected to the gate terminal (No. 6) of

transistor P_1 to form a current mirror, i.e., the current flowing through P_1 to charge C_1 will be essentially equal to the constant-current flow established through R_3, N_2 , and P_2 . A description of current-mirror operation with MOS transistors is given subsequently.

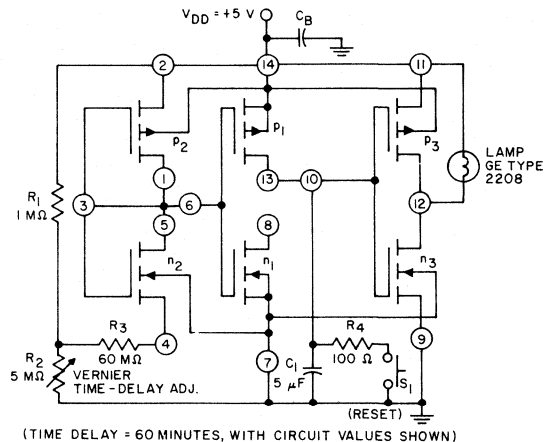


Fig. 26— Analog timer using CA3600E.

Oscillator Circuits

Oscillator circuits using COS/MOS transistor-pairs have been widely used for several years in clock and watch circuits because of their low power consumption and good frequency stability. Details of their operating theory and characteristics have been published.^{5,7}

The design of COS/MOS oscillator circuits, like the design of any oscillator circuit, involves the provision of an amplifying section to operate compatibly with an appropriate feedback network. A single stage amplifier using a COS/MOS transistor-pair has already been described. A suitable feedback network to insure stable oscillator performance is easily added, as illustrated in connection with the crystal oscillator circuit shown in Fig. 27. The familiar pi-network has been connected between the input and output terminals, points "D" and "G", to provide the required 180° phase shift for stable oscillator performance. The frequency-determining crystal is an integral part of the pi-network feedback circuit. The resistors R_1 and R_2 decrease the total power consumption of the oscillator at a particular supply voltage and enhance the frequency stability. Variable frequency oscillators can be built by replacing the crystal with an appropriate inductance and tuning the pi-network by conventional means.

Current Mirrors Using MOS Transistors

Monolithic linear IC's using bipolar transistors frequently employ so-called "current-mirror" circuits. The theory and practical applications of current mirrors using bipolar transistors have been described in the literature.² As shown in

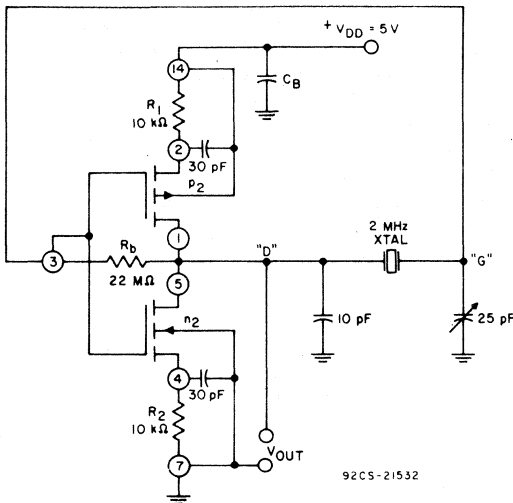


Fig. 27— Typical crystal-oscillator circuit using COS/MOS transistor-pair (1/3 CA3600E).

Fig. 28, a rudimentary form of "current-mirror" consists of a transistor Q_1 with a second transistor Q_2 connected as a diode. When both transistors have identical characteristics, a current I_1 forced to flow through Q_2 produces a current (I_2) of equal magnitude to flow in the collector of Q_1 (provided there is sufficient collector potential for Q_1). In a common form of application, a source of potential is used to force

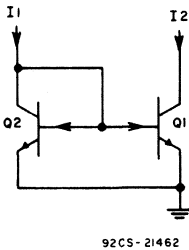


Fig. 28— Current mirror using n-p-n bipolar transistors.

constant-current flow I_1 , and thus to establish the flow of constant current I_2 through Q_1 . Arrangements of this generic current-mirror type are frequently used when Q_1 acts as the common-emitter impedance in a differential-amplifier circuit.

MOS transistors are also applicable as current mirrors, as shown in Fig. 29. The diode-connected MOS transistor N_2 functions as a transistor with 100 per-cent feedback. Therefore, the gate-to-source voltage (V_{GS}) in N_2 retains control of the drain current as in normal transistor action, i.e., $I_D \cong g_{fs} V_{GS}$, where g_{fs} is the forward transconductance of the device. If a current I_1 is forced into the diode-connected transistor (N_2), the gate-to-source voltage will rise until equilibrium is reached. Thus, a gate-to-source voltage is established in N_2 such that N_2 "sinks" the applied current I_1 .

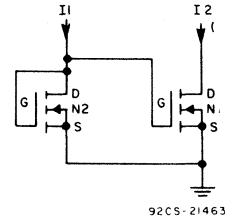


Fig. 29— Current mirror using n-channel MOS transistors

If the gate and source terminals of another transistor (N_1) are connected in shunt with the gate and source terminals of N_2 , as shown in Fig. 29, N_1 is also able to "sink" a mirror current approximately equal to that flowing in the drain lead of the diode-connected transistor N_2 . It is assumed that both MOS transistors have identical characteristics, a prerequisite that is essentially established by the monolithic IC fabrication technology used in manufacturing the CA3600E COS/MOS transistor array.

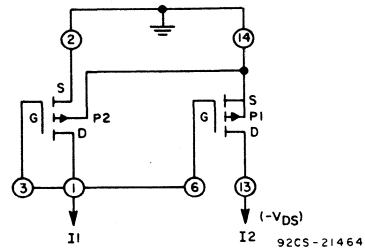


Fig. 30— Current mirror using p-channel MOS transistors in CA3600E.

Current mirrors can also be designed with p-channel MOS transistors as illustrated by the arrangement in Fig. 30 using transistors in the CA3600E. The characteristics of a current mirror using the p-channel transistors in the CA3600E are superior to those which can be achieved with a current mirror using the n-channel transistors because the characteristics of the p-channel transistors are more nearly matched. The data

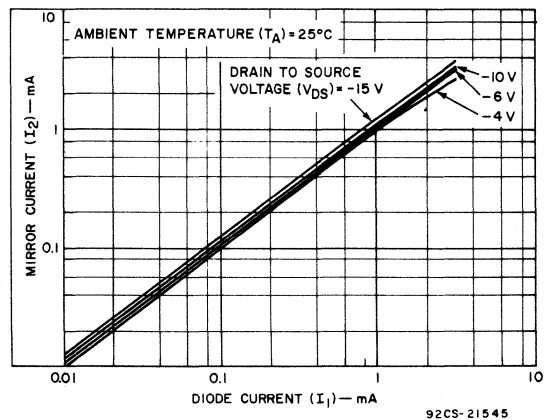


Fig. 31— Characteristics of current mirror circuit of Fig. 30 using p-channel transistors.

Linear Integrated Circuits

CA3600E

contained in Fig. 31 show the high degree of tracking between I_1 and I_2 for several values of drain voltage V_D . Fig. 32 also illustrates the fact that this high degree of tracking between I_1 and I_2 can be maintained to within about one per-cent despite wide variations in ambient temperature.

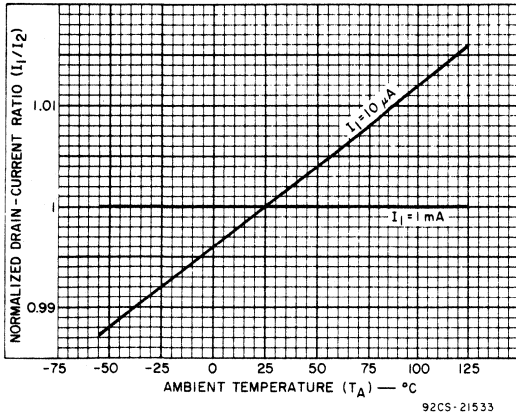


Fig. 32— Normalized drain current ratio vs. ambient temperature for typical current mirror using p-channel transistors (Fig. 30).

The op-amp circuit in Fig. 24 contains an illustrative example of a current-mirror circuit using two p-channel transistors in the CA3600E. Transistor P_2 serves as a constant-current source ($\cong 400 \mu A$) for the differential amplifier, consisting of transistors P_4 and P_5 and their drain-load network. Transistor P_2 is in a "mirrored" connection with transistor P_1 . A stabilized source of supply potential is developed across the zener diode (terminals 11 and 12 of the CA3083) and drives about $400 \mu A$ of current through R_6 and P_1 .

Complementary Current Mirrors Using COS/MOS Transistor-Pairs

COS/MOS transistor-pairs can be applied advantageously in the design of Complementary Current-Mirrors, as shown in Fig. 33. Transistors P_1 and N_1 are series-connected and biased for linear operation as previously described, so that there is a current flow I_{D1} through P_1 and N_1 . The potential developed between terminals 13 and 14 is applied as gate-source (2,3) voltage for P_2 , forcing "mirror" operation of P_2 to produce a current source I_{D2-p} equal to I_{D1} . Likewise, the potential developed between terminals 7 and 8 is applied as gate-source (3,4) voltage for N_2 forcing "mirror" operation of N_2 to produce a current-sink I_{D2-n} equal to I_{D1} .

A variant of this complementary current mirror is used in the analog timer circuit shown in Fig. 26. Transistors P_2 and N_2 are series-connected together with a 60-megohm resistor to establish their drain current at 5 nA. The potential developed across terminals 1 and 2 also appears as the gate-source voltage for transistor P_1 , thereby establishing a mirror-current source of 5 nA at terminal 13 to charge capacitor C_1 linearly. In this circuit, the "mirrored" current-sink available at terminal 8 (transistor N_1) is unused. This type of current-mirror configuration is exceptionally stable with temperature variations.

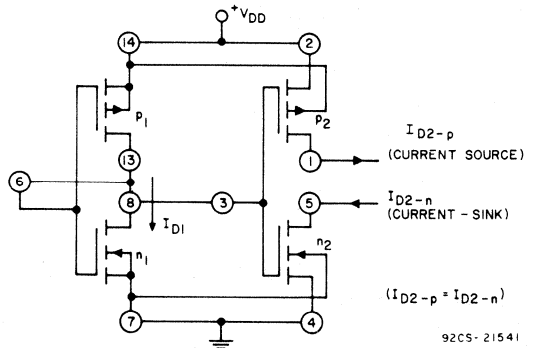


Fig. 33— Complementary current mirrors using COS/MOS transistor-pairs in CA3600E.

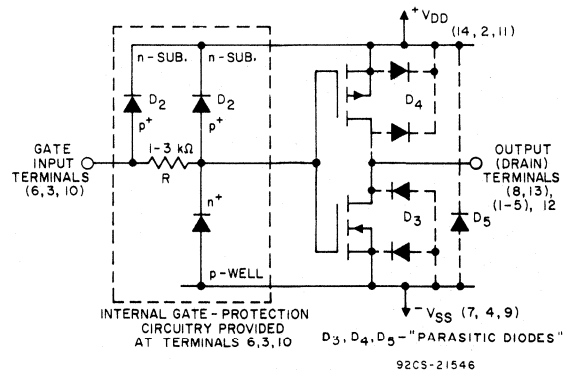


Fig. 34— Integral protection circuits used in CA3600E.

Considerations in Handling CA3600E Devices

Failure of the gate-channel oxide was a persistent problem in early MOS devices. The breakdown of the oxide is generally in the order of 100 volts, and the dc resistance is in the order of 10^{12} ohms. Because of this extremely high resistance, even a very-low-energy source (such as static charge) is capable of developing sufficient voltage to cause damage. Furthermore, the oxide can be punctured and damaged by a single voltage excursion beyond the breakdown limit.

Fig. 34 shows a protection circuit^{5,8} which is incorporated at each gate-lead of the CA3600E. A typical value of 1 to 3 kilohms is used for the input resistor R, which functions in combination with the capacitance of the gate and the associated protective diode to integrate and clamp input voltages to a safe level. This circuit also shows the "substrate diodes" (D_3 , D_4 , and D_5) which provide protection to the MOS channels at the output terminals.

Although the gate-protection system is very effective in guarding against damage due to static charges, it is prudent to observe the following precautions:^{5,9}

1. The leads of devices should be in contact with a conductive material, except when being tested or in actual operation. A conductive material such as "ECCOSORB LD26"* or equivalent is suggested for use during storage and/or handling. Devices should not be inserted in non-conductive containers such as conventional plastic "snow" or trays.
2. Soldering-iron tips, metal parts of fixtures and tools, and handling facilities should be grounded.
3. Devices should not be inserted into or removed from circuits with the power on because transient voltages may cause permanent damage.
4. Signals from low-impedance sources should not be applied to the gate terminals while the power supply is off. As a corollary, it follows that the power supply

should not be turned off while a signal from a low-impedance source is being applied to any gate terminal. When the V_{DD} supply is off, the positive "back-bias" voltage is removed from the cathode of diode D_2 (see Fig. 34). Consequently, an input signal with positive-going polarity can drive D_2 into conduction. Under these conditions a low-impedance signal source can provide sufficient current to permanently damage D_2 and/or melt aluminum interconnection paths. Therefore, if, in any system design using the CA3600E, any gate input excursion is expected to exceed $+V_{DD}$ or fall below $-V_{SS}$, the current through the input diodes should be limited to $100 \mu\text{A}$.

5. All unused gate-input terminals should be connected to V_{SS} (ground). When source terminals (e.g., Nos. 2 and 11) of p-channel transistors are unused in circuitry, they should be connected to terminal No. 14. Likewise, when source terminals (e.g., Nos. 4 and 9) of n-channel transistors are unused, they should be connected to terminal No. 7.
6. After CA3600E units have been mounted on circuit boards, proper handling precautions should still be observed. Until these subassemblies are inserted into a complete system, the board is no more than an extension of the device leads mounted on the board. It is a good practice to place conductive tape or jumpers on circuit-board terminals to "ground" gate terminals.
7. In some applications of the CA3600E separate positive and negative power supplies may be employed (e.g., see Fig. 22). In such applications provisions must be made so that the positive supply voltage is applied prior to the application of negative supply voltage and vice versa on shutdown. This precaution is necessary to avoid possible damage due to "latching" involving the substrate and protective diode circuits.

* Trade Mark: Emerson and Cumming, Inc.

Power Control Circuits Technical Data

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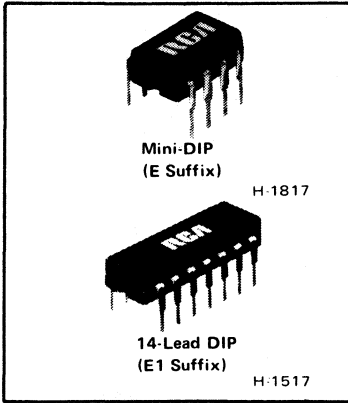
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CA3165



Electronic Switching Circuit

FEATURES:

- Switching initiated by damping of internal oscillator
- Proximity sensing of rotational motion
- Repeatable timing of switching states
- Five outputs — two complementary pairs and one non-inverting output (CA3165E1)
- Two outputs — one complementary pair (CA3165E)

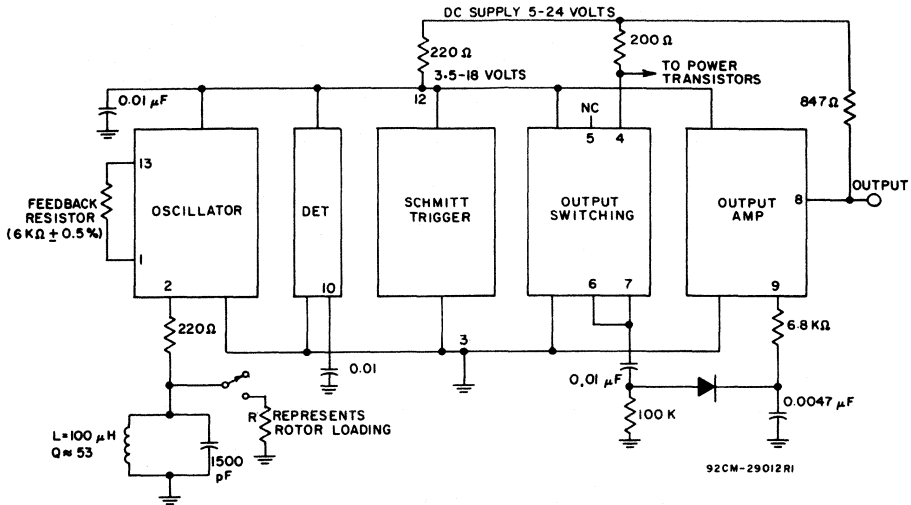
The RCA CA3165 is a single-chip electronic switching circuit intended primarily for ignition applications. It includes an oscillator that is amplitude-modulated by the rotor teeth of a distributor, a detector that develops the positive-going modulation envelope, a Schmitt trigger that eliminates switching uncertainties. Both types include two complementary high-current switched outputs for driving power transistors requiring up to 120 milliamperes. The

CA3165E also includes two complementary low-current outputs that incorporate internal current limiting and a non-inverting output amplifier with uncommitted input capable of switching 27 milliamperes.

The CA3165 is supplied in the 8-lead dual-in-line plastic package (Mini-DIP, E suffix) and in the 14-lead dual-in-line plastic package (E1 suffix).

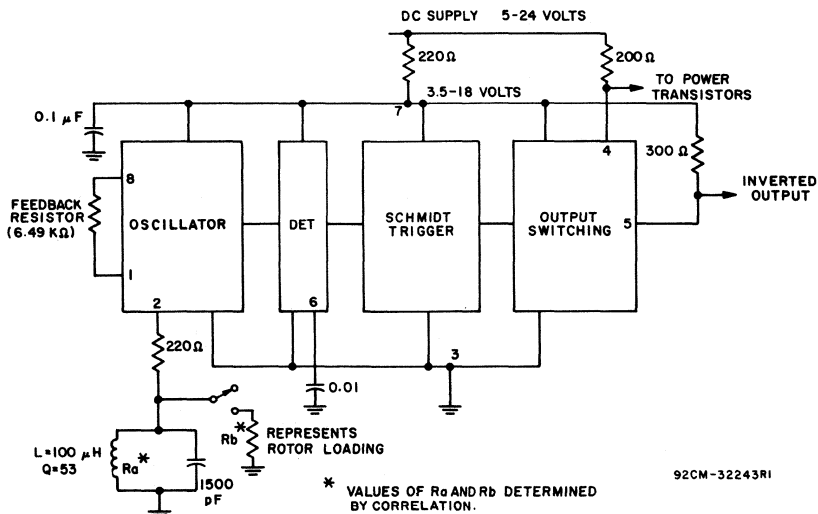
MAXIMUM RATINGS, Absolute-Maximum Values:

	CA3165E1	CA3165E		
DC Voltage (With reference to terminal 3):				
Terminal	4,6,8	4,5	24	V
Terminal	5,7,12	7	18	V
Terminal	9	—	1.5	V
CURRENT (At terminals indicated):				
Terminal	4,6	4,5	120	mA
Terminal	5,7	—	-0.1 to 0.1	mA
Terminal	8	—	30	mA
DEVICE DISSIPATION:				
Up to $T_A = 55^\circ\text{C}$			600	mW
Above $T_A = 55^\circ\text{C}$		derate linearly at	6.67	mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:				
Operating			-40 to +85	$^\circ\text{C}$
Storage			-65 to +150	$^\circ\text{C}$
LEAD TEMPERATURE (During soldering):				
At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10 seconds max.			265	$^\circ\text{C}$



Oscillator Condition	Terminal 10	Terminal 4	Terminal 5	Terminal 6	Terminal 7	Terminal 8
Unloaded	Low	High	High	Low	Low	Low
Loaded	High	Low	Low	High	High	High

Fig. 1 - Functional block diagram for CA3165E1



Oscillator Condition	Terminal 4	Terminal 5	Terminal 6
Unloaded	High	High	Low
Loaded	Low	Low	High

Fig. 2 - Functional block diagram for CA3165E

Linear Integrated Circuits

CA3165

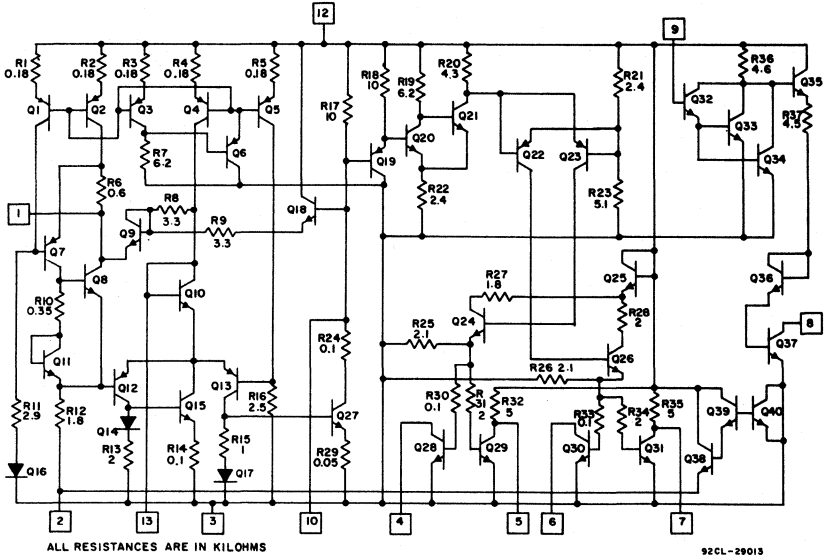


Fig. 3 - Schematic diagram for CA3165E1

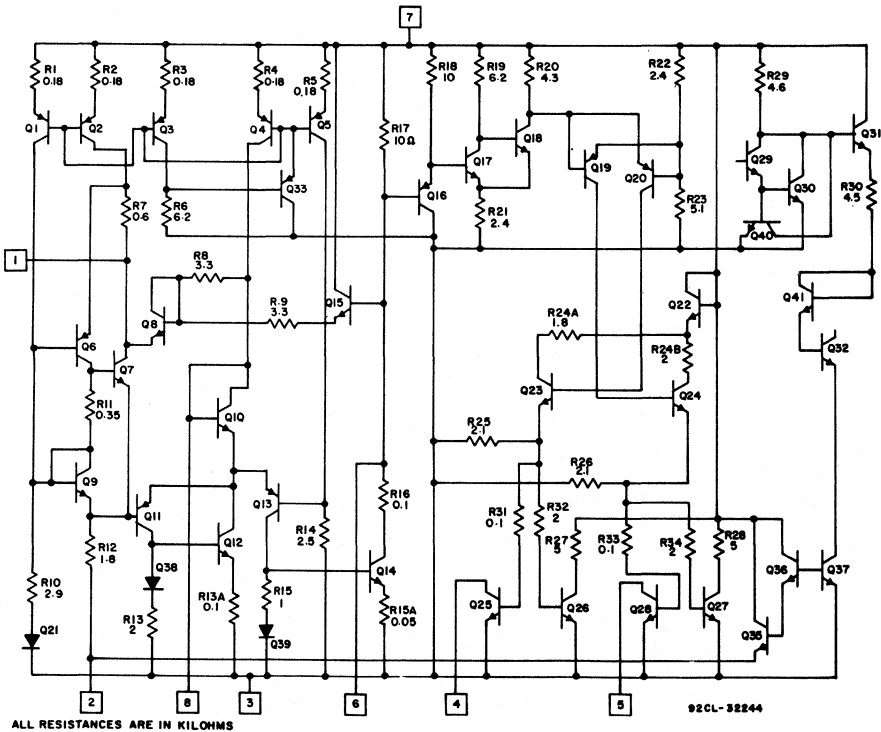


Fig. 4 - Schematic diagram for CA3165E

ELECTRICAL CHARACTERISTICS

At $T_A = 25^\circ\text{C}$, $V^+ = 13\text{ V}$, Measured in the circuit of Fig. 5 (CA3165E1) or Fig. 6 (CA3165E)

CHARACTERISTIC	TEST PERIOD	LIMITS						UNITS	
		CA3165E1			CA3165E				
		Min.	Typ.	Max.	Min.	Typ.	Max.		
Input Current at Term.*	Δ	Dwell	—	18.4	—	—	18.4	—	mA
		Spark	—	17.5	—	—	17.5	—	
Output Voltage at Term. 4	V_4	Dwell	12.8	—	—	12.8	—	—	V
		Spark	—	—	0.5	—	—	0.5	
Output Voltage at Term. 7	V_7	Dwell	—	—	1	—	—	—	V
Output Voltage at Term. 8	V_8	Dwell	—	—	0.9	—	—	—	V
		Portion of Spark	1.2	—	—	—	—	—	
Oscillator Voltage at Term. 2	V_2	Dwell	—	4.4	—	—	4.4	—	V_{p-p}
		Spark	—	0.6	—	—	0.6	—	

* Δ
 CA3165E 7 I_7
 CA3165E1 12 I_{12}

APPLICATION INFORMATION

Figs. 5 and 6 shows the application of the CA3165 in a typical ignition system.

TERMINAL DESCRIPTIONS		
Terminal		Function
CA3165E1	CA3165E	
1	1	Oscillator feedback resistor, R_1
2	2	220 Ω protective resistor to tank circuit
3	3	Ground
4	4	Direct output — R_7 load resistor 200 ohms \pm 5%, and R_8 to power Darlington 15 ohms \pm 10%
5	—	Direct output — low current — not connected
6	5	Inverted high current output
7	—	Inverted low current output through C_1 (0.01 μF) to D_3 and R_3 (100 K ohm)
8	—	Output amplifier output — through R_6 and R_5 (27 ohms and 820 ohms to supply)
9	—	Output amplifier input — through R_4 (6800 ohms) to D_3 and C_5 (0.0047 μF)
10	6	Detector output — C_2 to ground (0.0022 μF)
11	—	No connection
12	7	Circuit supply voltage through R_1 (220 ohms protective resistor) to automotive supply
13	8	Oscillator feedback resistor R_1 to terminal 1
14	—	No connection

CA3165

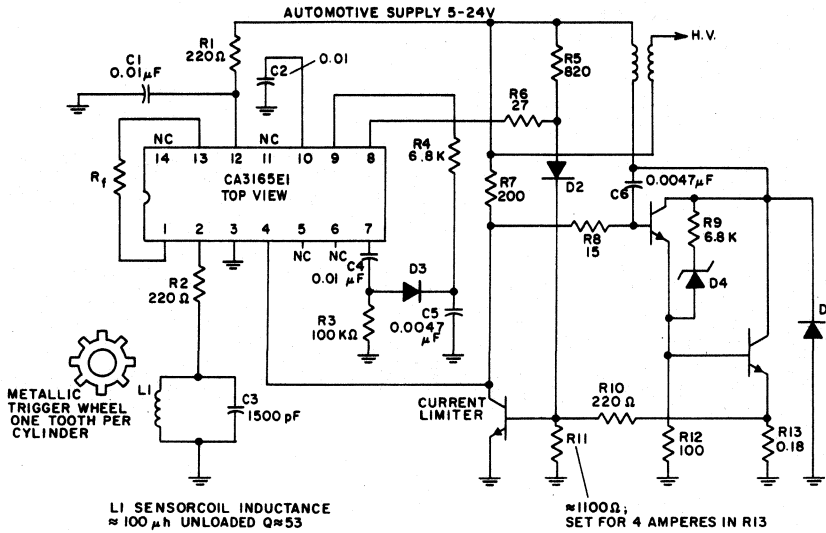


Fig. 5 - Typical ignition system using the CA3165E1

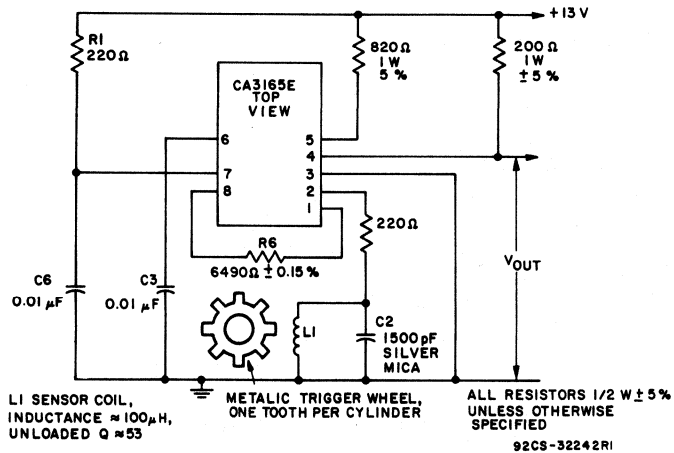


Fig. 6 - Typical ignition system using the CA3165E

APPLICATION INFORMATION

Figs. 5 and 6 shows the application of the CA3165 in a typical ignition system. The oscillator on the chip operates at about 400 kHz as determined by the tuned circuit L1, C3. The amplitude of the oscillation is detected on the chip and applied to a Schmitt trigger which sets the terminal voltage as shown in the chart in Figs. 1 and 2 for the unloaded condition of the oscillator. As a metallic tooth in the rotor passes the coil L1 eddy-current losses occur which reduce the Q of the resonant circuit and decrease the amplitude of the oscillations to a level

below that of a reference in the detector circuit. The output terminals are then switched to states as shown in the chart in Figs. 1 and 2 for the loaded condition of the oscillator. The oscillation is maintained at this lower amplitude by switching in additional feedback in the oscillator circuit. The fact that the oscillator continues to operate at some minimum level during this dwell period eliminates timing variations which would occur if the oscillator had to be re-started by random noise.

Spark occurs as terminal 4 is switched from high to low. The output amplifier clamps terminal 4 low through the regulator during the duration of the spark.

The Dwell period represents the time that terminal 10 (CA3165E1) or terminal 6 (CA3165E) is high, terminal 4 is low, and the coil is charged.

The value of the oscillator feedback, resis-

tor, R_f , is selected to set the dwell period. With a sintered-iron 8 f-tooth rotor, a typical value of R_f is 6500 ohms for 28.5 degrees of dwell out of a 45 degree cycle. For a star-type rotor and a particular coil in a typical distributor, the feedback resistor would be larger (typically 8800 ohms) depending on clearances, coil geometry and tooth shape.

Timing waveforms are shown in Fig. 7.

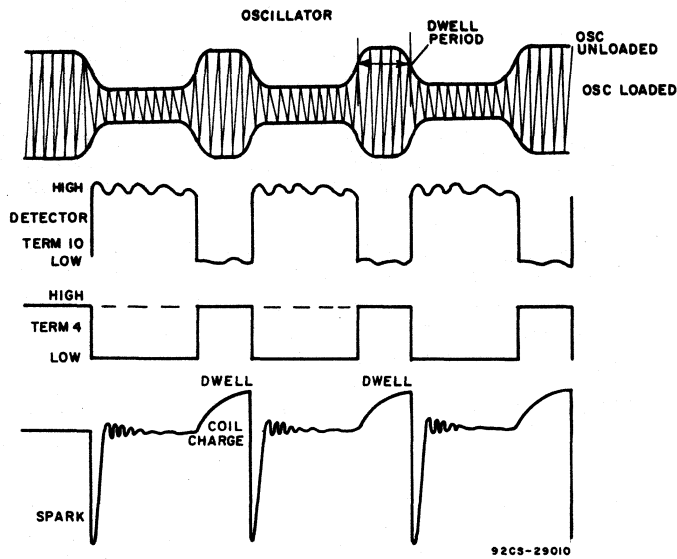
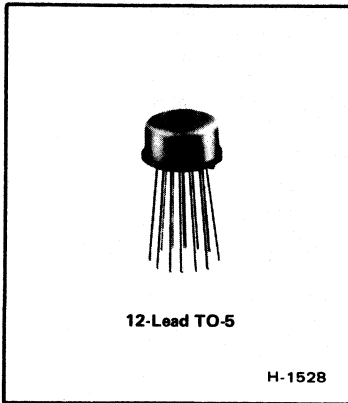


Fig. 7 - Timing sequence

CA3020, CA3020A



Multipurpose Wide-Band Power Amplifiers

For Military, Industrial, and Commercial Equipment at Frequencies up to 8 MHz

Features:

- High power output — class B amplifier. . .
 - CA3020 — 0.5 W typ. at $V_{CC} = +9$ V
 - CA3020A — 1.0 W typ. at $V_{CC} = +12$ V
- Wide frequency range. . .
 - Up to 8 MHz with resistive loads
- High power gain. . .75 dB typ.
- Single power supply for class B operation with transformer. . .
 - CA3020 — 3 to 9 V
 - CA3020A — 3 to 12 V
- Built-in temperature-tracking voltage regulator provides stable operation over -55°C to $+125^{\circ}\text{C}$ temperature range

The RCA-CA3020 and CA3020A are integrated-circuit, multi-stage, multipurpose, wide-band power amplifiers on a single monolithic silicon chip. They employ a highly versatile and stable direct-coupled circuit configuration featuring wide frequency range, high voltage and power gain, and high power output. These features plus inherent stability over a wide temperature range make the CA3020 and CA3020A extremely useful for a wide variety of applications in military, industrial, and commercial equipment.

The CA3020 and CA3020A are particularly suited for service as class B power amplifiers. The CA3020A can provide a maximum power output of 1 watt from a 12-volt dc supply with a typical power gain of 75 dB. The CA3020 provides 0.5-watt power output from a 9-volt supply with the same power gain.

These types are supplied in hermetically sealed TO-5 style 12-lead packages.

SCHEMATIC DIAGRAM FOR CA3020 AND CA3020A

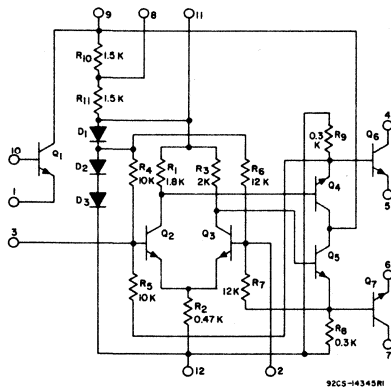


Fig. 1

The resistance values included on the schematic diagram have been supplied as a convenience to assist Equipment Manufacturers in optimizing the selection of "outboard" components of equipment designs. The values shown may vary as much as $\pm 30\%$.

RCA reserves the right to make any changes in the Resistance Values provided such changes do not adversely affect the published performance characteristics of the device.

Applications:

- AF power amplifiers for portable and fixed sound and communications systems
- Servo-control amplifiers
- Wide-band linear mixers
- Video power amplifiers
- Transmission-line driver amplifiers (balanced and unbalanced)
- Fan-in and fan-out amplifiers for computer logic circuits
- Lamp-control amplifiers
- Motor-control amplifiers
- Power multivibrators
- Power switches
- Companion Application Note, ICAN-5766, "Application of CA3020 and CA3020A Integrated Circuit Multipurpose Wide-Band Power Amplifiers"

Power Control Circuits

CA3020, CA3020A

ABSOLUTE-MAXIMUM RATINGS:

DISSIPATION:		WITHOUT HEAT SINK	WITH HEAT SINK
At $T_A = 25^\circ\text{C}$	1 W	At $T_C = 25^\circ\text{C}$	2 W
Above $T_A = 25^\circ\text{C}$	derate linearly 6.7 mW/ $^\circ\text{C}$	At $T_C = 25^\circ\text{C}$ to $T_C = 55^\circ\text{C}$	2 W
		Above $T_C = 55^\circ\text{C}$	derate linearly 16.7 mW/ $^\circ\text{C}$

TEMPERATURE RANGE:

Operating	-55°C to $+125^\circ\text{C}$
Storage	-65°C to $+150^\circ\text{C}$

MAXIMUM VOLTAGE RATINGS at $T_A = 25^\circ\text{C}$

The following chart gives the range of voltages which can be applied to the terminals listed vertically with respect to the terminals listed horizontally. For example, the voltage range of the vertical terminal 1 with respect to terminal 12 is 0 to +10 volts.

MAXIMUM CURRENT RATINGS

TERMINAL No.	1	2	3	4	5	6	7	8	9	10	11	12
1		*	*	*	*	*	*	*	Δ 0 -10/-12	+3 Note 1	*	+10 0
2			*	*	*	*	*	*	*	*	*	+2 -2
3				*	*	*	*	*	*	*	*	+2 -2
4					Δ +18/+25 0	*	*	*	*	*	*	Δ +18/+25 0
5						*	*	*	*	*	*	+3 Note 2
6							Δ 0 -18/-25	*	*	*	*	+3 Note 2
7								*	*	*	*	Δ +18/+25 0
8									Note 3	*	*	Note 3 0
9										+10 0	Note 1 0	+10/+12 0
10											*	+10 0
11												*
12												REF. SUB- STRATE

TERMINAL No.	I_{IN} mA	I_{OUT} mA
1	-	20
2	-	-
3	-	-
4	300	-
5	-	300
6	-	300
7	300	-
8	-	-
9	20	-
10	1	-
11	20	-
12	-	-

Note 1: This voltage is established by the maximum current rating.

Note 2: The emitters of Q_6 and Q_7 may be returned to a negative voltage supply through emitter resistors. Current into terminal No.9 should not be exceeded and the total device dissipation should not be exceeded.

Note 3: Terminal No.8 may be connected to terminals Nos.9, 11, or 12.

* Voltages are not normally applied between these terminals. Voltages appearing between these terminals will be safe if the specified limits between all other terminals are not exceeded.

Δ Higher value is for CA3020A.

Linear Integrated Circuits

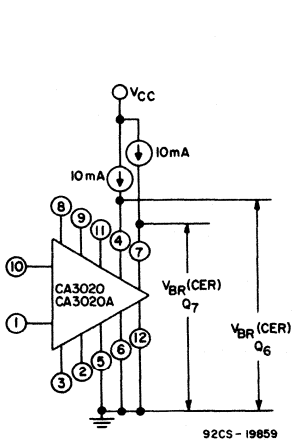
CA3020, CA3020A

ELECTRICAL CHARACTERISTICS AT $T_A = 25^\circ\text{C}$

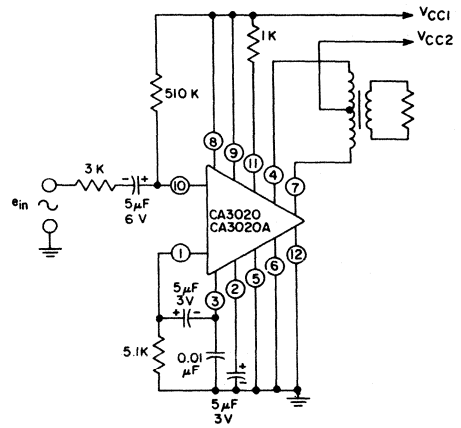
CHARACTERISTICS	SYMBOLS	TEST CONDITIONS			LIMITS CA3020			LIMITS CA3020A			UNITS
		CIRCUIT AND PROCEDURE	DC SUPPLY VOLTAGE		MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
			FIG.	V _{CC1}							
Collector-to-Emitter Breakdown Voltage, Q ₆ & Q ₇ at 10 mA	V _{(BR)CER}	2 _a	-	-	18	-	-	25	-	-	V
Collector-to-Emitter Breakdown Voltage, Q ₁ at 0.1 mA	V _{(BR)CEO}	-	-	-	10	-	-	10	-	-	V
Idle Currents, Q ₆ & Q ₇	I ₄ IDLE I ₇ IDLE	8	9.0	2.0	-	5.5	-	-	5.5	-	mA
Peak Output Currents, Q ₆ & Q ₇	I ₄ PK I ₇ PK	8	9.0	2.0	140	-	-	180	-	-	mA
Cutoff Currents, Q ₆ & Q ₇	I ₄ CUTOFF I ₇ CUTOFF	8	9.0	2.0	-	-	1.0	-	-	1.0	mA
Differential Amplifier Current Drain	I _{CC1}	8	9.0	9.0	6.3	9.4	12.5	6.3	9.4	12.5	mA
Total Current Drain	I _{CC1} + I _{CC2}	8	9.0	9.0	8.0	21.5	35.0	14.0	21.5	30.0	mA
Differential Amplifier Input Terminal Voltages	V ₂ V ₃	8	9.0	2.0	-	1.11	-	-	1.11	-	V
Regulator Terminal Voltage	V ₁₁	8	9.0	2.0	-	2.35	-	-	2.35	-	V
Q ₁ Cutoff (Leakage) Currents: Collector-to-Emitter	I _{CEO}	-	10.0	-	-	-	100	-	-	100	μA
Emitter-to-Base	I _{EBO}	-	3.0	-	-	-	0.1	-	-	0.1	
Collector-to-Base	I _{CBO}	-	3.0	-	-	-	0.1	-	-	0.1	
Forward Current Transfer Ratio, Q ₁ at 3 mA	h _{FE1}	-	6.0	-	30	75	-	30	75	-	
Bandwidth at -3 dB Point	BW	9	6.0	6.0	-	8	-	-	8	-	MHz
Maximum Power Output	P _{O(MAX)}	10	6.0	6.0	200	300 ^a	-	200	300 ^a	-	mW
			9.0	9.0	400	550 ^a	-	400	550 ^a	-	
			9.0	12.0	-	-	-	800	1000 ^b	-	
Sensitivity for P _{OUT} = 400 mW	e _{IN}	10	9.0	9.0	-	35 ^a	55	-	-	-	mV
Sensitivity for P _{OUT} = 800 mW	e _{IN}	10	9.0	12.0	-	-	-	-	50 ^b	100	mV
Input Resistance--- Terminal 3 to Ground	R _{IN3}	11	6.0	6.0	-	1000	-	-	1000	-	Ω
Junction-to-Case Thermal Resistance	θ _{J-C}	-	-	-	-	-	60	-	-	60	°C/W

^a R_{CC} = 130 Ω

^b R_{CC} = 200 Ω



92CS-19859



92CS-15233

a. Collector-to-Emitter Breakdown Voltage (Q₆ and Q₇) Circuit

b. Typical Audio Amplifier Circuit Utilizing the CA3020 or CA3020A As An Audio Preamplifier and Class B Power Amplifier

Fig.2

TYPICAL PERFORMANCE DATA*

An External Radiator is Recommended for High Ambient Temperature Operation

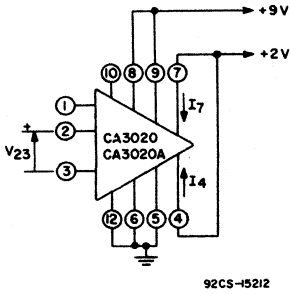
CHARACTERISTICS	SYMBOLS	CA3020	CA3020A	UNITS
Power Supply Voltage	V_{CC1}	9.0	9.0	^m V V
	V_{CC2}	9.0	12.0	
Zero Signal Current	Diff. Ampl. I_{CC1}	15	15	mA
	Output Ampl. I_{CC2}	24	24	
Maximum Signal Current	Diff. Ampl. I_{CC1}	16	16.6	mA
	Output Ampl. I_{CC2}	125	140	
Maximum Power Output at THD = 10%	P_O	550	1000	mW
Sensitivity	e_{IN}	35	45	mV
Power Gain	G_P	75	75	dB
Input Resistance	R_{IN}	55	55	k Ω
Efficiency	η	45	55	%
Signal-to-Noise Ratio	S/N	70	66	dB
THD at 150 mW level		3.1	3.3	%
Test Signal Frequency from 600 Ω Generator		1000	1000	Hz
Equivalent Collector-to-Collector Load Resistance	R_{CC}	130	200	Ω

* Refer to Figs.8 through 12 for Measurement and Symbol Information.

Linear Integrated Circuits

CA3020, CA3020A

TYPICAL TRANSFER CHARACTERISTICS



a. Test Setup

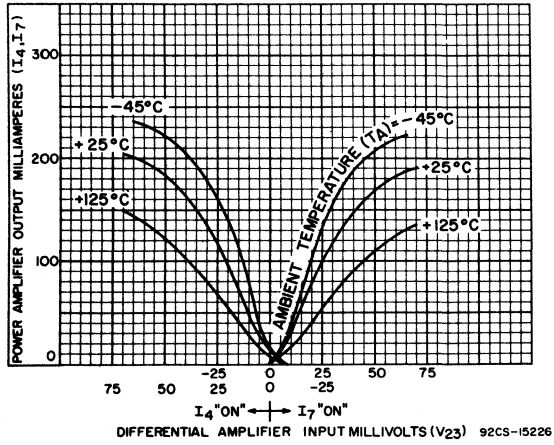
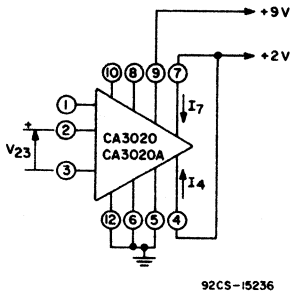


Fig.3

b. Characteristics with R_{10} shorted out



a. Test Setup

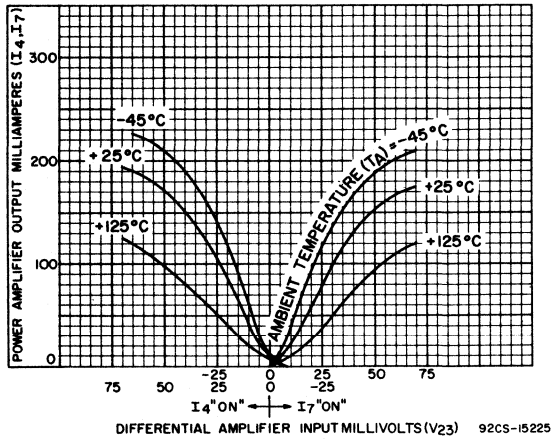
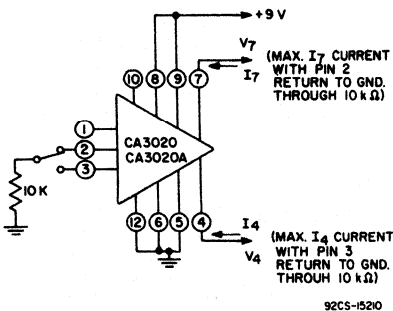


Fig.4

b. Characteristics with R_{10} in circuit

"MINIMUM DRIVE" TYPICAL CURRENT-VOLTAGE SATURATION CURVE



a. Test Setup

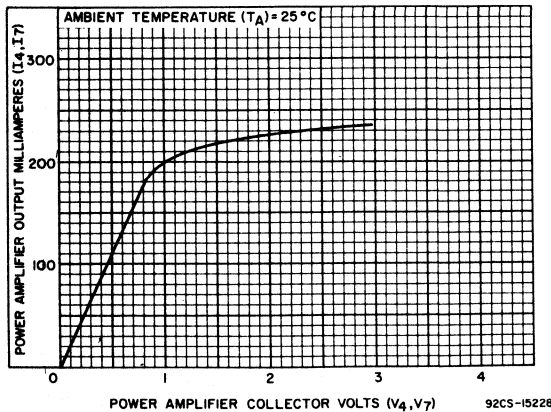


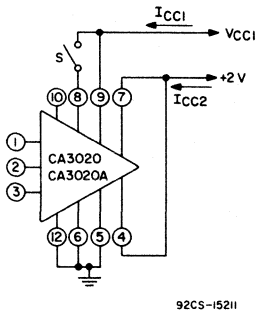
Fig.5

b. Characteristic

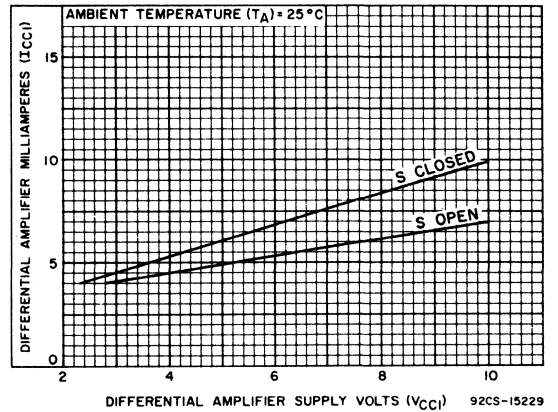
Power Control Circuits

CA3020, CA3020A

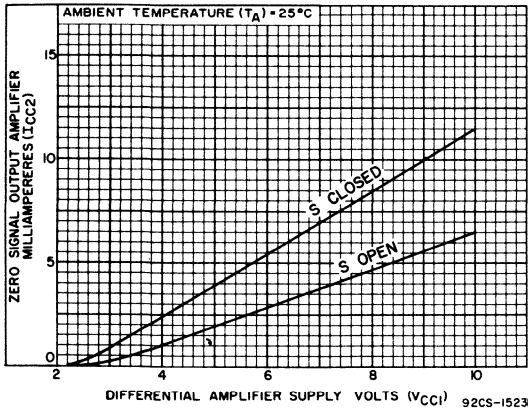
ZERO SIGNAL AMPLIFIER CURRENT vs DIFFERENTIAL AMPLIFIER SUPPLY VOLTAGE



a. Test Setup



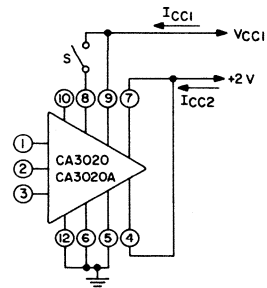
b. Differential Amplifier Characteristics



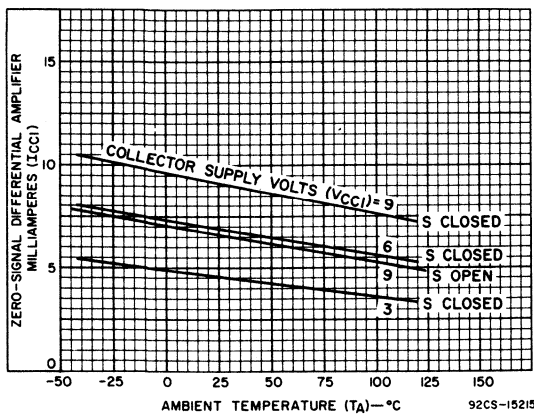
c. Output Amplifier Characteristics

Fig. 6

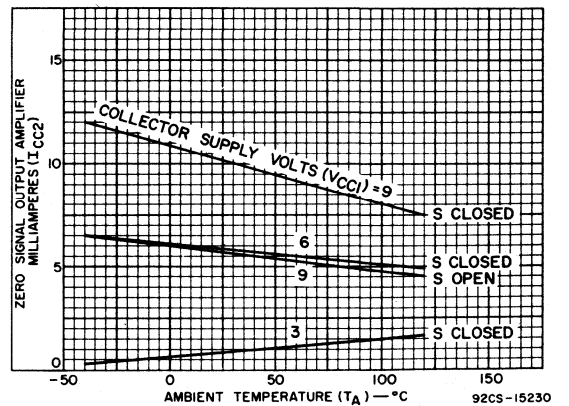
ZERO SIGNAL AMPLIFIER CURRENT vs AMBIENT TEMPERATURE



a. Test Setup



b. Differential Amplifier Characteristics



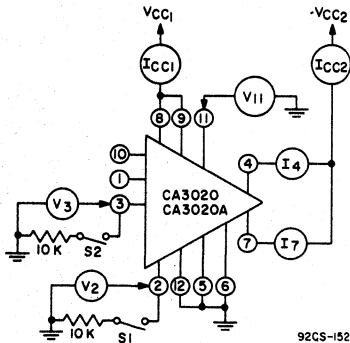
c. Output Amplifier Characteristics

Fig. 7

Linear Integrated Circuits

CA3020, CA3020A

STATIC CURRENT AND VOLTAGE TEST CIRCUIT



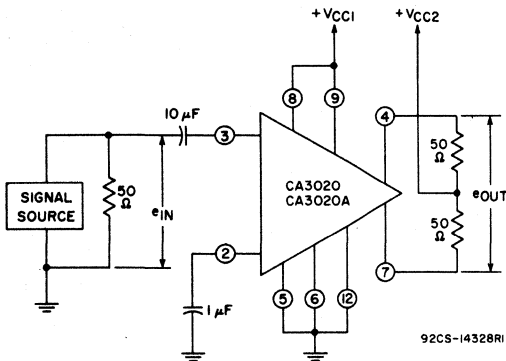
92CS-15214

CURRENTS OR VOLTAGES	S1	S2
I ₄ -IDLE	open	open
I ₇ -IDLE	open	open
I ₄ -PEAK	open	close
I ₇ -PEAK	close	open
I ₄ -CUTOFF	close	open
I ₇ -CUTOFF	open	close

CURRENTS OR VOLTAGES	S1	S2
I _{CC1}	open	open
I _{CC2}	open	open
V ₂	open	open
V ₃	open	open
V ₁₁	open	open

Fig.8

MEASUREMENT OF BANDWIDTH AT -3 dB POINTS



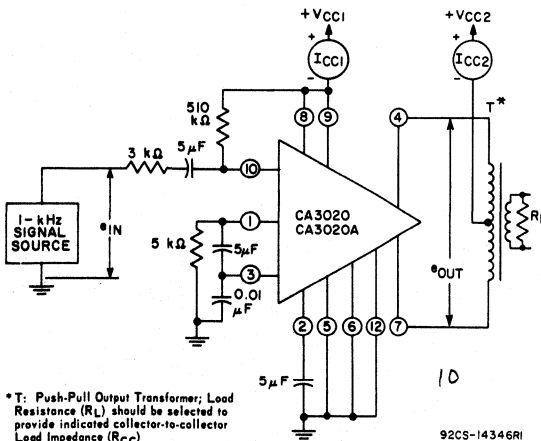
92CS-14328RI

Fig.9

PROCEDURES:

1. Apply desired value of V_{CC1} and V_{CC2} .
2. Apply 1 kHz input signal and adjust for $e_{IN} = 5$ mV (rms).
3. Record the resulting value of e_{OUT} in dB (reference value).
4. Vary input-signal frequency, keeping e_{IN} constant at 5 mV, and record frequencies above and below 1 kHz at which e_{OUT} decreases 3 dB below reference value.
5. Record bandwidth as frequency range between -3 dB points.

MEASUREMENTS OF ZERO-SIGNAL DC CURRENT DRAIN, MAXIMUM-SIGNAL DC CURRENT DRAIN, MAXIMUM POWER OUTPUT, CIRCUIT EFFICIENCY, SENSITIVITY, AND TRANSDUCER POWER GAIN



92CS-14346RI

*T: Push-Pull Output Transformer; Load Resistance (R_L) should be selected to provide indicated collector-to-collector Load Impedance (R_{CL}).

PROCEDURES:

Zero-Signal DC Current Drain

1. Apply desired Value of V_{CC1} and V_{CC2} and reduce e_{IN} to 0V
2. Record resulting values of I_{CC1} and I_{CC2} in mA as Zero-Signal DC Current Drain.

Fig.10

Maximum-Signal DC Current Drain, Maximum Power Output, Circuit Efficiency, Sensitivity, and Transducer Power Gain

1. Apply desired value of V_{CC1} and V_{CC2} and adjust e_{IN} to the value at which the Total Harmonic Distortion in the output of the amplifier = 10%
2. Record resulting value of I_{CC1} and I_{CC2} in mA as Maximum-Signal DC Current Drain
3. Determine resulting amplifier power output in watts and record as Maximum Power Output (P_{OUT})
4. Calculate Circuit Efficiency (η) in % as follows:

$$\eta = 100 \frac{P_{OUT}}{V_{CC1}I_{CC1} + V_{CC2}I_{CC2}}$$

where P_{OUT} is in watts, V_{CC1} and V_{CC2} are in volts, and I_{CC1} and I_{CC2} are in amperes.

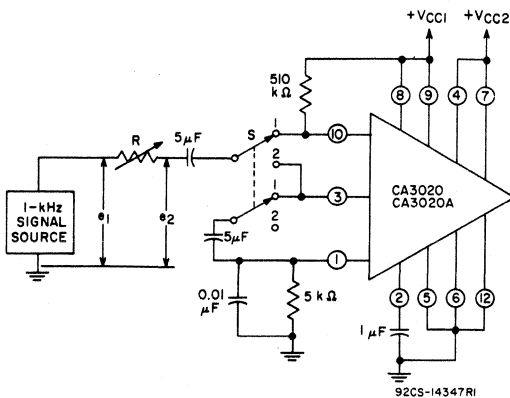
5. Record value of e_{IN} in mV² (rms) required in Step 1 as Sensitivity (e_{IN})

6. Calculate Transducer Power Gain (G_p) in dB as follows:

$$G_p = 10 \log_{10} \frac{P_{OUT}}{P_{IN}}$$

$$\text{where } P_{IN} \text{ (in mW)} = \frac{e_{IN}^2}{3000 + R_{IN}(10)}$$

MEASUREMENT OF INPUT RESISTANCE



92CS-14347R1

Fig.11

PROCEDURES:

Input Resistance Terminal 10 to Ground (R_{IN10})
1. Apply desired value of V_{CC1} and V_{CC2} and set S in Position 1

2. Adjust 1-kHz input for desired signal level of measurement

3. Adjust R for $e_2 = e_1/2$

4. Record resulting value of R as R_{IN10}

Input Resistance Terminal 3 to Ground (R_{IN3})

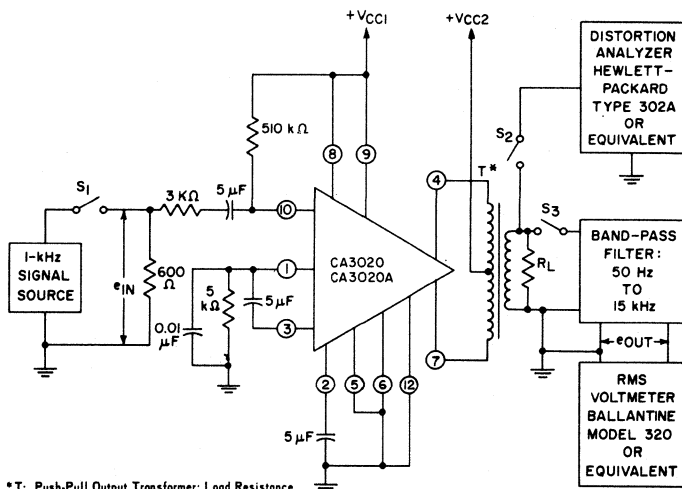
1. Apply desired value of V_{CC1} and V_{CC2} set S in Position 2

2. Adjust 1-kHz input for desired signal level of measurement

3. Adjust R for $e_2 = e_1/2$

4. Record resulting value of R as R_{IN3}

MEASUREMENT OF SIGNAL-TO-NOISE RATIO
AND TOTAL HARMONIC DISTORTION



*T: Push-Pull Output Transformer; Load Resistance (R_L) should be selected to provide indicated collector-to-collector Load Impedance (RCC)

92CM-14329R1

PROCEDURES:

Signal-to-Noise Ratio

1. Close S_1 and S_3 ; open S_2
2. Apply desired values of V_{CC1} and V_{CC2}
3. Adjust e_{IN} for an amplifier output of 150mW and record resulting value of E_{OUT} in dB as e_{OUT1} (reference value)

4. Open S_1 and record resulting value of e_{OUT} in dB as e_{OUT2}

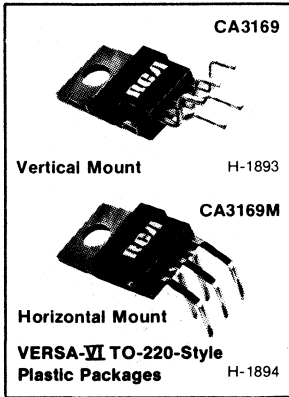
$$5. \text{Signal-to-Noise Ratio (S/N)} = 201 \log_{10} \frac{e_{OUT1}}{e_{OUT2}}$$

Total Harmonic Distortion

1. Close S_1 and S_2 ; open S_3
2. Apply desired values of V_{CC1} and V_{CC2}
3. Adjust e_{IN} for desired level amplifier output power
4. Record Total Harmonic Distortion (THD) in %

Fig.12

CA3169



Solenoid and Motor Driver (1/2 H Driver)

Features:

- Chip encapsulated in a 5-lead plastic TO-220-style package (VERSA-VI)
- Output short-circuit protection
- Thermal overload protection
- Solenoid inductive "kick" protection with internal-clamp diodes
- Output sink and source capacity of 600-mA minimum overtemperature
- Horizontal and vertical mounting packages available
- Separate sink circuit and source circuit, each individually controlled

The RCA-CA3169 is a monolithic integrated circuit capable of driving lamps and other devices that can be changed between two states (on or off). Transistors, SCR's, and triacs are some of the solid-state devices that can be controlled by the CA3169. This device can also control relays, solenoids (latching or non-latching), motors (DC - forward and reverse) and DC stepping motors.

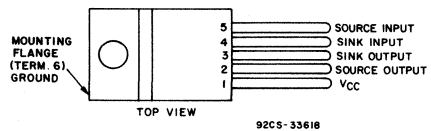
The CA3169 contains a separate source-driver circuit with internal current-limiting protection and a separate sink-driver circuit. The sink driver contains an energy-absorbing diode to protect the device against any inductive "kick" during state changes. The CA3169 is protected against overvoltage conditions on the output drivers and overtemperature conditions (thermal-shutdown protection).

The input operating levels are TTL compatible. The source and sink outputs are in their off condition (non-conducting) when their respective inputs are in a HI state, or open-circuited. The outputs are in their on state (conducting) when their respective inputs are LO. The VERSA-VI package is available with two lead configurations. The CA3169 has a vertical-mount lead form, and the CA3169M has a horizontal-mount lead form.

- Inputs can be driven by TTL logic levels and CMOS logic levels
- Low $V_{CE(sat)}$

Applications:

- Latching solenoid driver (single and multiple)
- Non-latching solenoid driver
- Relay driver
- Lamp controller
- Lamp driver
- Motor controller (forward and reverse)
- Stepper motor controller
- On-off logic controllers (TTL logic)
- Intermediate power driver
- Triac, SCR, and transistor drivers



TERMINAL ASSIGNMENT

MAXIMUM RATINGS, Absolute-Maximum Values:

SUPPLY VOLTAGE (Pin 1 to GND)	Positive	.41 V DC
	Negative	.14 V DC
SINK CURRENT		1.9 A
SOURCE CURRENT		Controlled by Internal Current Limiting
INPUT VOLTAGE:		
SINK INPUT (Pin 4 to GND)		17 V
SOURCE INPUT (Pin 5 to GND)		17 V
MAXIMUM FORWARD CURRENT—Diode D1		2.5 A
MAXIMUM FORWARD CURRENT—Diode D2		3 A
POWER DISSIPATION, P _D at T _A =90°C		15 W
THERMAL RESISTANCE, JUNCTION TO CASE		4°C/W
JUNCTION TEMPERATURE		150°C
OPERATING TEMPERATURE		-40° to +85°C
STORAGE TEMPERATURE		-55° to +150°C
LEAD TEMPERATURE (DURING SOLDERING):		
At distance 1/16 ± 1/32 in. (1.59 ± 0.79 mm)		
from case for 10 s max.		.265°C

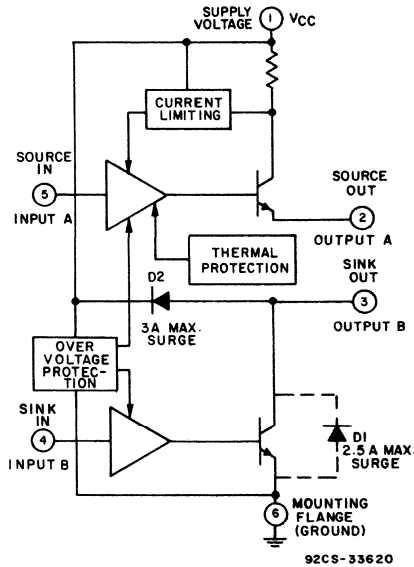
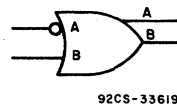


Fig. 1 - 1/2 H driver function diagram.

TRUTH TABLE FOR SOLENOID DRIVER

TTL Logic Conditions: $0 \leq V_L \leq 0.8, 1.9 \leq V_H \leq 5.5$

INPUT A SOURCE IN	INPUT B SINK IN	OUTPUT A SOURCE OUT	OUTPUT B SINK OUT
V _L	V _L	HIGH (ON)	LOW (ON)
V _L	V _H	HIGH (ON)	(OFF)
V _H	V _L	(OFF)	LOW (ON)
V _H	V _H	(OFF)	(OFF)



Linear Integrated Circuits

CA3169

ELECTRICAL CHARACTERISTICS at $T_A=25^\circ\text{C}$, $V_{CC}=10.5\text{ V to }18\text{ V}$

Unless otherwise specified

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
Output Leakage Current, Pin 2 See Fig. 6	Inputs Open $V_{CC}=4\text{ V to }18\text{ V}$ Source and Sink Loads= $20\ \Omega$	-110	± 0.5	110	μA
Output Leakage Current, Pin 3 See Fig. 6	Inputs Open $V_{CC}=4\text{ V to }18\text{ V}$ Source and Sink Loads= $20\ \Omega$	-110	± 0.5	110	
Thermal Resistance, Junction to Case θ_{JC}		—	3	4	$^\circ\text{C/W}$
Quiescent Current, Pin 1 See Fig. 5	Device "ON" Input Terminals Shorted, $V_{CC}=14\text{ V}$	—	70	100	mA
Quiescent Current, Pin 1 See Fig. 4	Device "OFF" Input Terminals Open, $V_{CC}=14\text{ V}$	—	17	40	
Thermal Shutdown Temperature	R_L =Short Circuit	128	140	162	$^\circ\text{C}$
Overvoltage Shutdown-Circuit Upper Trip Point, Pin 1 Voltage See Fig. 8	$R_L=20\ \Omega$	20	25	27	V
Overvoltage Shutdown-Circuit Lower Trip Point, Pin 1 Voltage See Fig. 8	$R_L=20\ \Omega$	18	21.4	23	
Input Logic Levels: Source Input - Pin 5, Sink Input - Pin 4					
Input Low Threshold Sink or Source V_{IL}	$V_{CC}=14\text{ V}$ See Note 1	—	0.4	0.8	V
Input High Threshold Sink or Source V_{IH}	$V_{CC}=14\text{ V}$ See Note 2	1.9	2.4	—	
Input Low Current Sink or Source I_{LL}	$V_{IN} \leq 0.4\text{ V}$	-0.9	-0.3	—	mA
Input High Current Sink or Source I_{IH}	$V_{IN} \leq 5.5\text{ V}$	-110	-23	110	μA

NOTE 1: I_{SOURCE} or $I_{SINK} \leq 600\text{ mA}$, $V_{OS} \leq 1.5\text{ V}$, $V_{SINK} \leq 0.75\text{ V}$.

NOTE 2: I_{SOURCE} or $I_{SINK} \leq 100\ \mu\text{A}$, $V_{SOURCE} = \text{GND}$, for V_{SINK} $20\ \Omega$ to V_{CC} .

ELECTRICAL CHARACTERISTICS (Cont'd)

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
Source Outputs					
Output Voltage, V_{OS} Pin 2 See Note 3 See Fig. 7	Referenced to V_{CC} with $I_{SOURCE} = 600$ mA	—	1	1.6	V
Short-Circuit Current Limit, Pin 2 to Ground		0.65	1.11	2.6	A
Turn-On Delay to Output-On, Pin 2	$C_L = 100$ pF, $R_L = 33 \Omega$	—	0.45	5.6	μs
Turn-Off Delay to Output-Off Pin 2	$C_L = 100$ pF, $R_L = 33 \Omega$	—	5	55	
Sink Outputs					
Output Saturation Voltage V_3 See Note 3 See Fig. 10	$I_{SINK} = 600$ mA, $V_{IN} \leq 0.4$ V	—	0.3	0.85	V
Output Saturation Voltage V_3 See Note 3 See Fig. 10	$I_{SINK} = 1000$ mA, $V_{IN} \leq 0.4$ V	—	0.8	1.65	
Turn-On Delay to Output-On Pin 3 (T_{ON})	$C_L = 100$ pF, $R_L = 33 \Omega$ to V_{CC}	—	0.45	5.6	μs
Turn-Off Delay to Output-Off Pin 3 (T_{OFF})	$C_L = 100$ pF, $R_L = 33 \Omega$ to V_{CC}	—	0.95	25	

NOTE 3: Measured over temperature range of $-40^\circ C$ to $85^\circ C$.

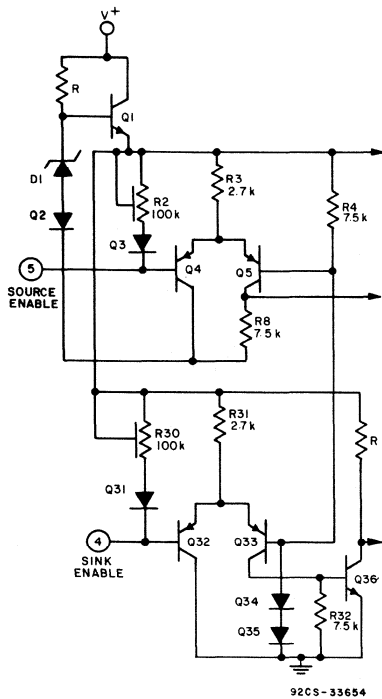


Fig. 2 - Detailed schematic of the input circuit for CA3169.

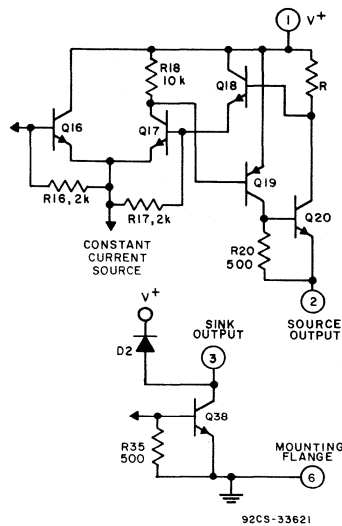


Fig. 3 - Detailed schematic of the output circuit for CA3169.

TEST CIRCUITS ($V_{CC} = V_{IN} = \text{PIN 1 VOLTAGE}$)

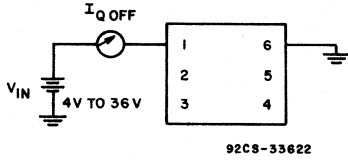


Fig. 4 - Quiescent current device "OFF".

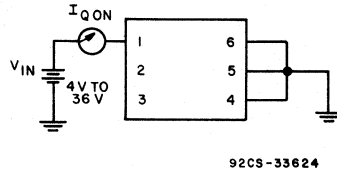


Fig. 5 - Quiescent current device "ON".

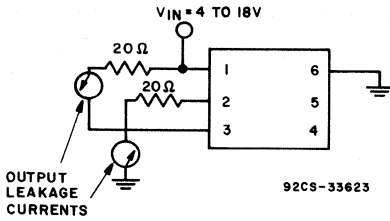


Fig. 6 - Output leakage currents.

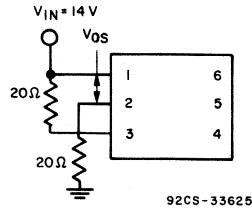
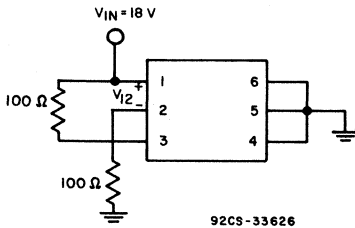


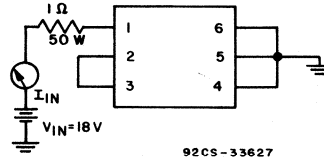
Fig. 7 - Output source voltage (referenced to V_{CC}).



PROCEDURE

1. Measure V_{12} .
2. Increase V_{CC} until $V_{12} \geq 2 \text{ V}$.
3. Measure V_{CC} ; this voltage is the high trip point. Pin 2 should be off; i.e., pin 3 should be high.
4. Observe and measure the voltage at pin 3.
5. Decrease V_{CC} until pin 3 switches, i.e., $\leq 18 \text{ V}$. The supply voltage will be the low trip point voltage.

Fig. 8 - Overvoltage protection.



When V_{CC} is turned on, I_{IN} should be equal to or greater than 1 A. Thermal shutdown will operate properly if the input current drops below 0.5 A (0.3 A typ.) in 10 to 15 seconds. Cover the unit during this test in the event that the thermal shutdown is not operating properly.

Fig. 9 - Thermal shutdown.

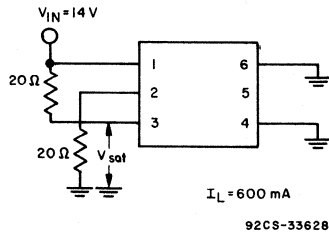
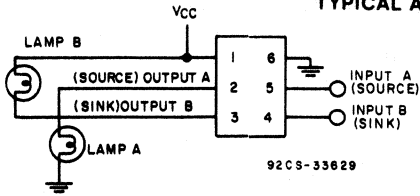


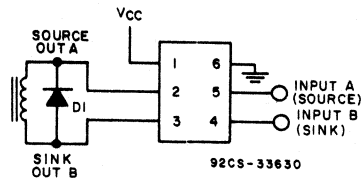
Fig. 10 - Output saturation voltage.

TYPICAL APPLICATIONS



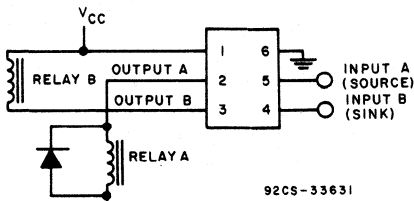
When input A goes low, lamp A will light. When input B goes low, lamp B will light.

Fig. 11 - Lamp driver.



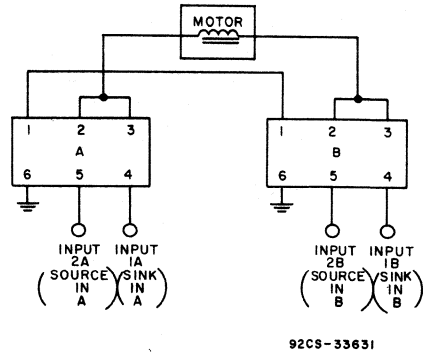
Input A and input B must both be low for the solenoid to switch.

Fig. 12 - Non-latching solenoid.



Relay A will close when input A goes low. Relay B will close when input B goes low. Both relays will close when both inputs go low.

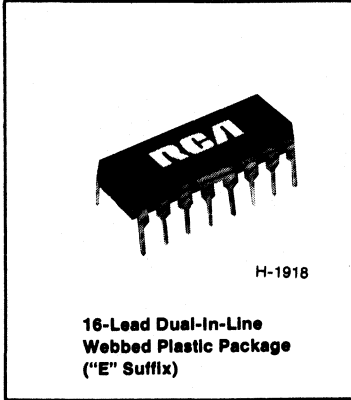
Fig. 13 - Relay driver.



When opposing inputs go low, the motor will switch direction; if source input A and sink input B both go low, current will flow from A to B. If source input B and sink input A both go low, current will flow from B to A.

Fig. 14 - Motor driver or latching solenoid driver.

CA3219E



Quad-Power NAND Driver

For Interfacing Low-Level Logic to High Current Loads

Features:

- Driven outputs capable of switching 600 mA load currents without spurious changes in output state
- Inputs compatible with TTL or 5-volt CMOS logic
- Suitable for resistive or inductive loads

The RCA CA3219E[®] quad power NAND driver contains four NAND gate switches for interfacing low-level logic to inductive and resistive loads such as: relays, solenoids, AC and DC motors, heaters, incandescent displays, and vacuum fluorescent displays.

Diodes in the outputs protect the IC against voltage transients due to switching inductive loads.

To allow for maximum heat transfer from the chip, the two

•Formerly RCA Dev. Type No. TA10982.

center leads are directly connected to the die substrate and to the ground bond pads. In free air, junction-to-air thermal resistance (θ_{J-A}) is 50° C/W* (typical).

The CA3219E is supplied in the 16-lead dual-in-line plastic package with webbed-lead construction.

* This coefficient can be lowered to 40° C/W (typical) by suitable design of the PC board to which the CA3219E is soldered.

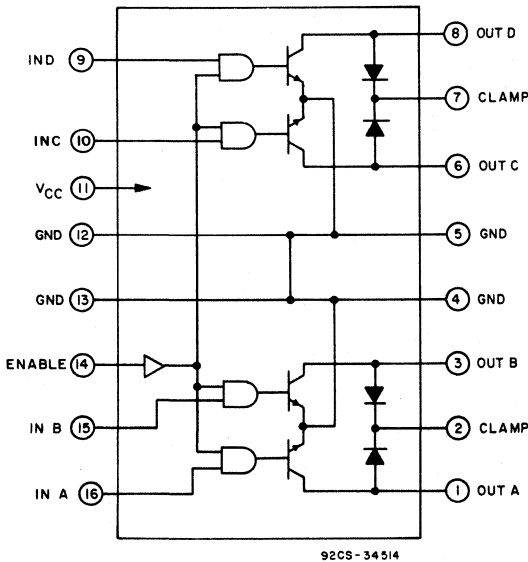


Fig. 1 - Block diagram for the CA3219E.

TRUTH TABLE

ENABLE	IN	OUT
H	H	L
H	L	H
L	X	H

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$:

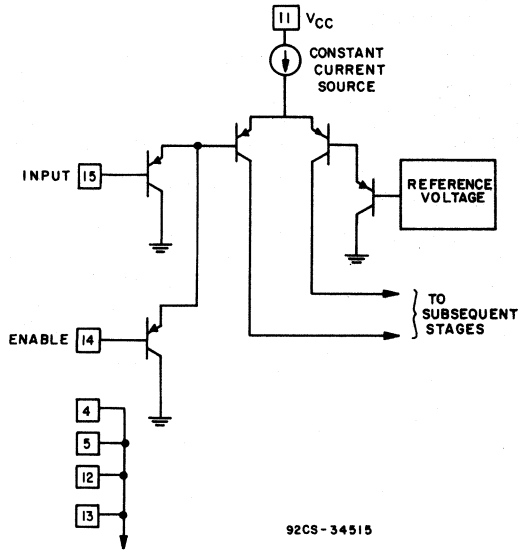
Logic Supply Voltage (V_{CC})	7 V
Logic Input Voltage (V_{IN})	15 V
Output Voltage (V_{CEX})	50 V _{DC}
Output Sustaining Voltage (V_{CC}) _{sus}	35 V _{DC}
Output Current (I_O)	1 ADC
Power Dissipation (P_D)	
Up to 55°C	1.5 W
Above 55°C	derate linearly at 16.6 mW/ $^\circ\text{C}$
Up to 90°C with heat sink	derate linearly at 25 mW/ $^\circ\text{C}$
Ambient Temperature Range:	
Operating	-40 to $+85^\circ\text{C}$
Storage	-55 to $+150^\circ\text{C}$
Maximum Junction Temperature ($T_{\theta J}$)	$+150^\circ\text{C}$
Maximum Thermal Resistance	
Junction-to-Air (θ_{J-A})	60 $^\circ\text{C}/\text{W}$
Junction-to-Case (θ_{J-C})	
to pins 4, 5, 12, 13 at seat	12 $^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V_{CC} = 5\text{ V}$

CHARACTERISTIC	LIMITS		UNITS
	MIN.	MAX.	
Output Leakage Current (I_{CEX}) $V_{CE} = 50\text{ V}$ $V_{IN} = 0.8\text{ V}$	—	100	μA
Output Sustaining Voltage $V_{CE(sus)}$ $I_C = 100\text{ mA}$ $V_{IN} = 0.8\text{ V}$	25	—	V
Collector Emitter Saturation Voltage $V_{CE(sat)}$ $I_C = 100\text{ mA}$ $V_{IN} = 2.4\text{ V}$	—	0.3	V
$I_C = 400\text{ mA}$ $V_{IN} = 2.4\text{ V}$	—	0.5	V
$I_C = 600\text{ mA}$ $V_{IN} = 2.4\text{ V}$	—	0.7	V
Input Low Voltage V_{IL}	—	0.8	V
Input Low Current I_{IL} $V_{IN} = 0.8\text{ V}$	—	+10	μA
Input High Voltage V_{IH} $I_C = 600\text{ mA}$	2	—	V
Input High Current I_{IH} $I_C = 700\text{ mA}$; $V_{IN} = 5.5\text{ V}$	—	40	μA
Supply Current — All Outputs ON, $I_{CC(ON)}$ $I_C = 700\text{ mA}$; $V_{CC} = V_{IH} = 5.5\text{ V}$	—	80	mA
Supply Current — All Outputs OFF, $I_{CC(OFF)}$	—	5	mA
Clamp Diode Leakage Current I_R $V_R = 50\text{ V}$	—	100	μA
Clamp Diode Forward Voltage V_F $I_F = 1\text{ A}$	—	1.5	V
$I_F = 1.5\text{ A}$	—	2	V
Turn-On Delay t_{PHL}		30	μs
Turn-Off Delay t_{PLH}			

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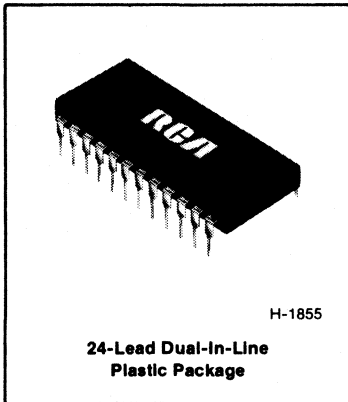
CA3219E



92CS - 34515

Fig. 2 - Schematic of one input section.

Speed-Control System



Features

- Low power dissipation
- I²L control logic
- Power-ON reset
- On-chip oscillator for system time reference
- Single line command
- Amplitude encoded control signals
- Transient compensated input commands
- Controlled acceleration mode
- Internal redundant brake and low speed disable
- Braking disable

The RCA-CA3228 is a monolithic I²L integrated circuit designed as an automotive speed-control system.

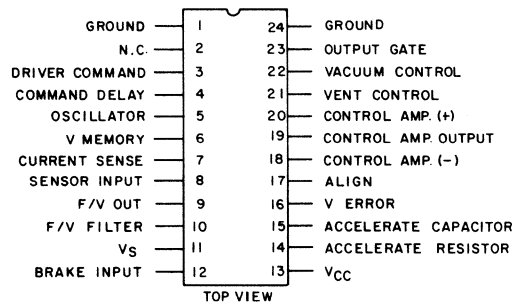
The system monitors vehicle speed and compares it to a set reference speed. Any deviation in vehicle speed causes a servo mechanism to open or close the engine throttle as required to eliminate the speed error. The reference speed is set by the driver to hold the existing speed and stored in a 9-bit counter.

The reference speed can be altered by the ACCEL and COAST driver commands. The ACCEL command causes the vehicle to accelerate at a controlled rate while the

COAST command causes the servo to relax completely forcing the vehicle to slow down. Application of the brake causes the servo to relax immediately and places the system into the standby mode while the RESUME command returns the vehicle to the last stored speed.

Vehicle speed and driver commands are input into the integrated circuit via external sensors. Actuators are needed to convert the output signals into the mechanical action necessary to control vehicle speed.

The CA3228 is supplied in a 24-lead plastic package (E suffix).



TERMINAL ASSIGNMENT

Linear Integrated Circuits

CA3228

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A=25^\circ\text{C}$

DC SUPPLY VOLTAGE RANGE (V_{DD})	7.4 to 9 V
DC SUPPLY CURRENT RANGE (I_{DD})	7.5 to 25 mA
POWER DISSIPATION PER PACKAGE:	
For $T_A=-40^\circ\text{C}$ to 55°C	125 mW
For $T_A=55^\circ\text{C}$ to 70°C	Derate linearly at 3.3 mW/ $^\circ\text{C}$
TEMPERATURE RANGE:	
OPERATING	-40 to +85 $^\circ\text{C}$
STORAGE	-65 to +150 $^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance $1/16 \pm 1/32$ in. (1.59 ± 0.79 mm) from case for 10 s max.	+265 $^\circ\text{C}$

SWITCHING CHARACTERISTICS, $T_A=25^\circ\text{C}$, $V_{DD}=7.4$ to 9 V

ACCEL	Input Hold Time	50 ms
COAST	Input Hold Time	50 ms
RESUME	Input Hold Time	330 ms
ON	Input Hold Time	50 ms
OFF	Input Hold Time	50 ms
INTERNAL OSCILLATOR FREQUENCY:		
C=0.005 μF at Pin 5		10,000 Hz
Speed Input Frequency		32 to 222 Hz

SYSTEM PERFORMANCE, $T_A=25^\circ\text{C}$, $V_{DD}=8.2$ V, $f_M=10$ kHz, $f_S=2.22$ Hz/mph

SPEED RESOLUTION	0.45 mph
MINIMUM OPERATING SPEED	25 mph
MAXIMUM STORED SPEED	100 mph
REDUNDANT BRAKE SPEED	11 mph

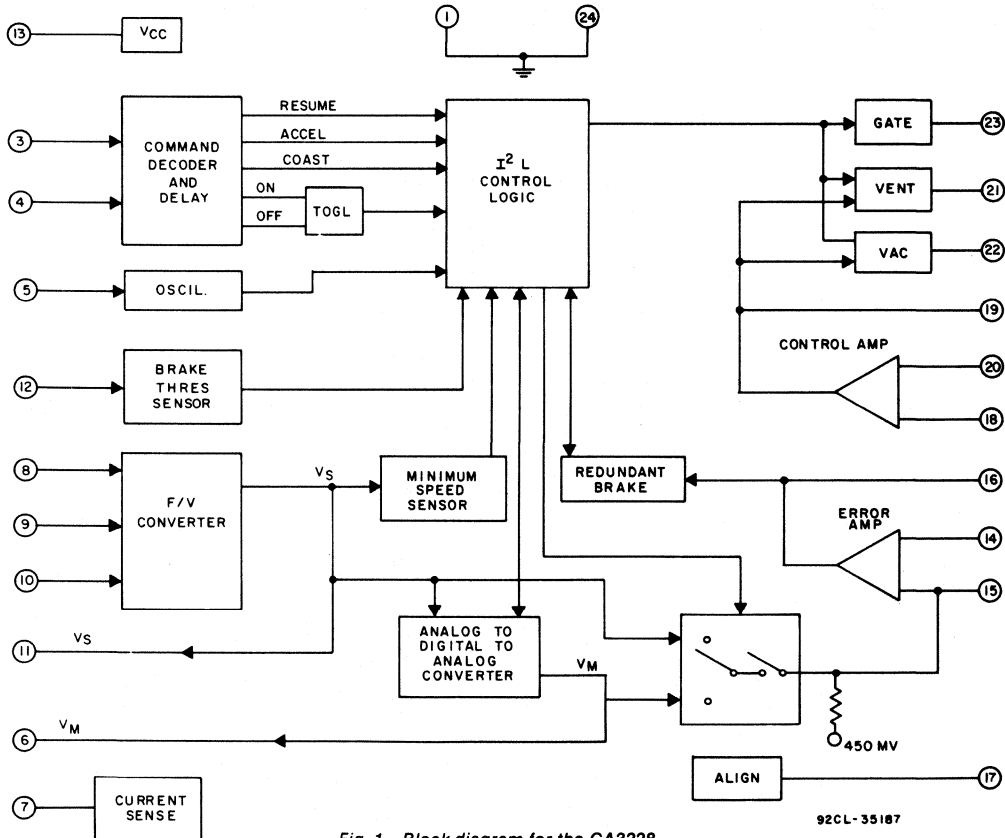


Fig. 1 - Block diagram for the CA3228.

92CL-35187

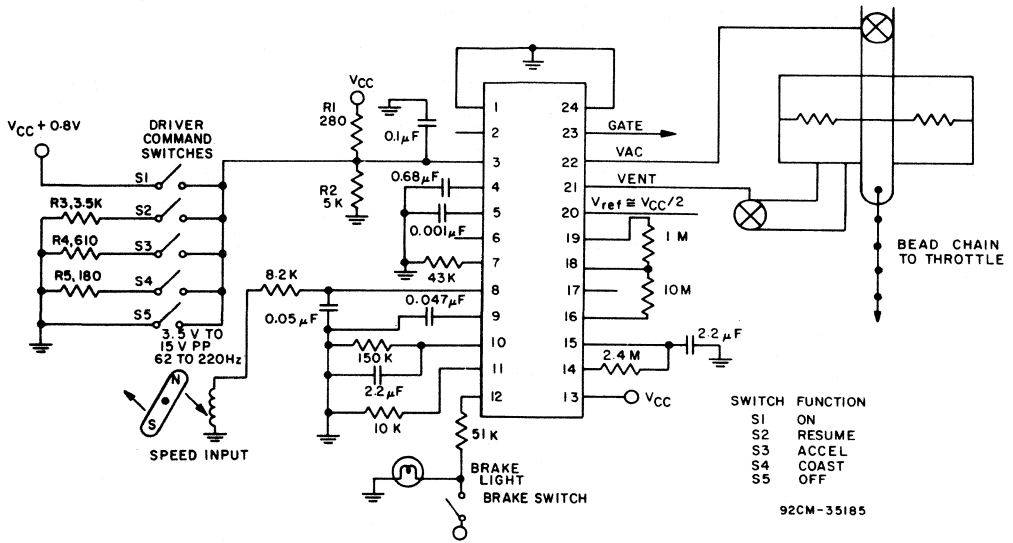
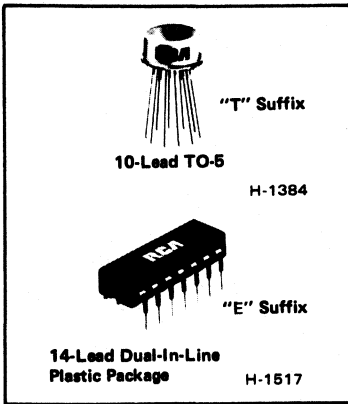


Fig. 2 - Typical automotive speed-control application.

Linear Integrated Circuits

CA723, CA723C Types



Voltage Regulators

For Regulated Output Voltages Adjustable from 2 V to 37 V at Output Currents up to 150 mA Without External Pass Transistors

Features:

- Up to 150 mA output current
- Positive and negative voltage regulation
- Regulation in excess of 10A with suitable pass transistors
- Input and output short-circuit protection
- Load and line regulation: 0.03%
- Direct replacement for 723 and 723C industry types
- Adjustable output voltage: 2 to 37 V

Applications:

- Series and shunt voltage regulator
- Floating regulator
- Switching voltage regulator
- High-current voltage regulator
- Temperature controller

RCA-CA723 and CA723C are silicon monolithic integrated circuits designed for service as voltage regulators at output voltages ranging from 2 to 37 volts at currents up to 150 milliamperes.

Each type includes a temperature-compensated reference amplifier, an error amplifier, a power series pass transistor, and a current-limiting circuit. They also provide independently accessible inputs for adjustable current limiting and remote shutdown and, in addition, feature low standby current drain, low temperature drift, and high ripple rejection.

The CA723 and CA723C may be used with positive and negative power supplies in a wide variety of series, shunt,

switching, and floating regulator applications. They can provide regulation at load currents greater than 150 milliamperes and in excess of 10 amperes with the use of suitable n-p-n or p-n-p external pass transistors.

The CA723 and CA723C are supplied in the 10-lead TO-5-style package (T suffix), and the 14-lead dual-in-line plastic package (E suffix), and are direct replacements for industry types 723, 723C, μ A723, and μ A723C in packages with similar terminal arrangements. They are also available in chip form (“H” suffix).

All types are rated for operation over the full military-temperature range of -55°C to $+125^{\circ}\text{C}$.

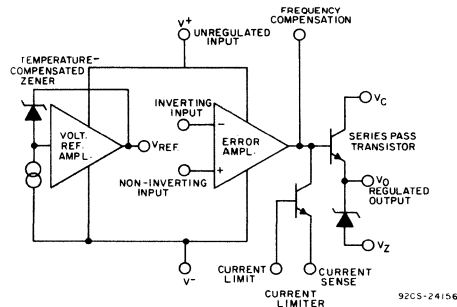


Fig. 1 — Functional diagram of the CA723 and CA723C.

Power Control Circuits

CA723, CA723C Types

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE (Between V^+ and V^- Terminals)	40	V
PULSE VOLTAGE FOR 50-ms PULSE WIDTH (Between V^+ and V^- Terminals)	50	V
DIFFERENTIAL INPUT-OUTPUT VOLTAGE	40	V
DIFFERENTIAL INPUT VOLTAGE:		
Between Inverting and Non- Inverting Inputs	± 5	V
Between Non-Inverting Input and V^-	8	V
CURRENT FROM ZENER DIODE TERMINAL (V_Z)	25	mA
CURRENT FROM VOLTAGE REFERENCE TERMINAL (V_{REF})	15	mA

DEVICE DISSIPATION:

Up to $T_A = 25^\circ\text{C}$ -		
CA723T, CA723CT	800	mW
CA723E, CA723CE	1000	mW
Above $T_A = 25^\circ\text{C}$ -		
CA723T, CA723CT	Derate linearly	6.3 mW/ $^\circ\text{C}$
CA723E, CA723CE	Derate linearly	8.3 mW/ $^\circ\text{C}$

AMBIENT TEMPERATURE

RANGE (All Types):		
Operating	-55 to +125	$^\circ\text{C}$
Storage	-65 to +150	$^\circ\text{C}$

LEAD TEMPERATURE

(During Soldering):		
At a distance $1/16'' \pm 1/32''$ (1.59 ± 0.79 mm) from case for 10 seconds max.	+265	$^\circ\text{C}$

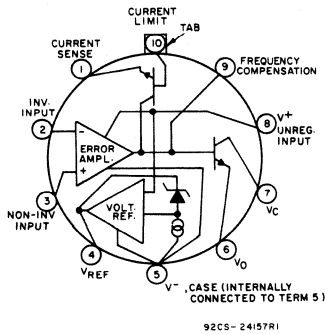


Fig. 2 - Terminal arrangement of the CA723T and CA723CT in the TO-5 style package.

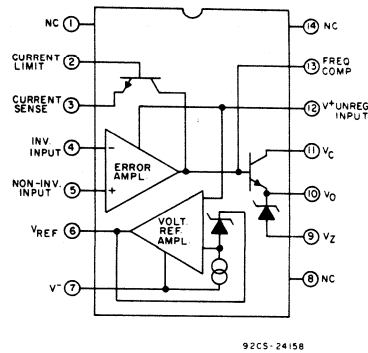


Fig. 3 - Terminal arrangement of the CA723E and CA723CE in the dual-in-line plastic package.

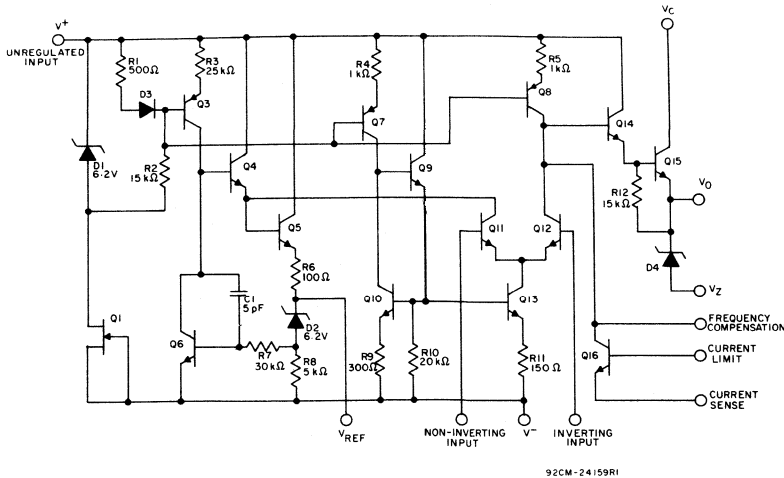


Fig. 4 - Equivalent schematic diagram of the CA723 and CA723C.

Linear Integrated Circuits

CA723, CA723C Types

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V^+ = V_C = V_I = 12\text{ V}$, $V^- = 0$, $V_O = 5\text{ V}$,
 $I_L = 1\text{ mA}$, $C_1 = 100\text{ pF}$, $C_{REF} = 0$, $R_{SCP} = 0$, unless otherwise specified. Divider
 impedance $R_1 R_2 / (R_1 + R_2)$ at non-inverting input, Term. 5, = $10\text{ k}\Omega$ (see Fig. 23).

CHARACTERISTIC	TEST CONDITIONS	LIMITS						UNITS
		CA723			CA723C			
		Min.	Typ.	Max.	Min.	Typ.	Max.	
Quiescent Regulator Current, I_Q	$I_L = 0$, $V_I = 30\text{ V}$	—	2.3	3.5	—	2.3	4	mA
Input Voltage Range, V_I		9.5	—	40	9.5	—	40	V
Output Voltage Range, V_O		2	—	37	2	—	37	V
Differential Input-Output Voltage, $V_I - V_O$		3	—	38	3	—	38	V
Reference Voltage, V_{REF}		6.95	7.15	7.35	6.8	7.15	7.5	V
Line Regulation (See Note 1)	$V_I = 12$ to 40 V	—	0.02	0.2	—	0.1	0.5	% V_O
	$V_I = 12$ to 15 V	—	0.01	0.1	—	0.01	0.1	
	$V_I = 12$ to 15 V , $T_A = -55$ to $+125^\circ\text{C}$	—	—	0.3	—	—	—	
	$V_I = 12$ to 15 V , $T_A = 0$ to 70°C	—	—	—	—	—	0.3	
Load Regulation (See Note 1)	$I_L = 1$ to 50 mA	—	0.03	0.15	—	0.03	0.2	% V_O
	$I_L = 1$ to 50 mA , $T_A = -55$ to $+125^\circ\text{C}$	—	—	0.6	—	—	—	
	$I_L = 1$ to 50 mA , $T_A = 0$ to 70°C	—	—	—	—	—	0.6	
Output-Voltage Temp. Coefficient, ΔV_O	$T_A = -55$ to $+125^\circ\text{C}$	—	0.002	0.015	—	—	—	%/ $^\circ\text{C}$
	$T_A = 0$ to 70°C	—	—	—	—	0.003	0.015	
Ripple Rejection (See Note 2)	$f = 50\text{ Hz}$ to 10 kHz	—	74	—	—	74	—	dB
	$f = 50\text{ Hz}$ to 10 kHz , $C_{REF} = 5\mu\text{F}$	—	86	—	—	86	—	

Power Control Circuits

CA723, CA723C Types

ELECTRICAL CHARACTERISTICS (Cont'd)

CHARACTERISTIC	TEST CONDITIONS	LIMITS						UNITS
		CA723			CA723C			
		Min.	Typ.	Max.	Min.	Typ.	Max.	
Short-Circuit Limiting Current, I_{LIM}	$R_{SCP} = 10 \Omega$, $V_O = 0$	—	65	—	—	65	—	mA
Equivalent Noise RMS Output Voltage, V_N (See Note 2)	BW = 100 Hz to 10 kHz, $C_{REF} = 0$	—	20	—	—	20	—	μV
	BW = 100 Hz 10 kHz, $C_{REF} = 5 \mu F$	—	2.5	—	—	2.5	—	

Note 1: Line and load regulation specifications are given for condition of a constant chip temperature. For high-dissipation conditions, temperature drifts must be separately taken into account.

Note 2: For C_{REF} , see Fig. 23.

TYPICAL CHARACTERISTICS CURVES FOR TYPE CA723

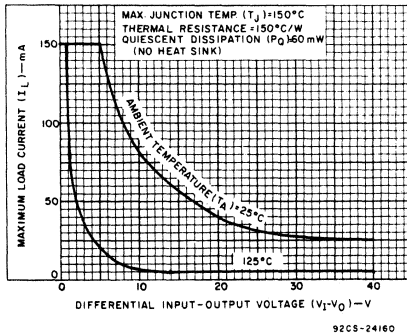


Fig. 5 - Max. load current vs differential input-output voltage.

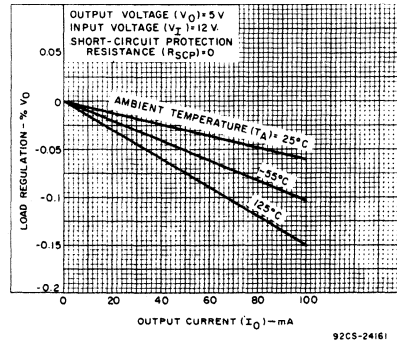


Fig. 6 - Load regulation without current limiting.

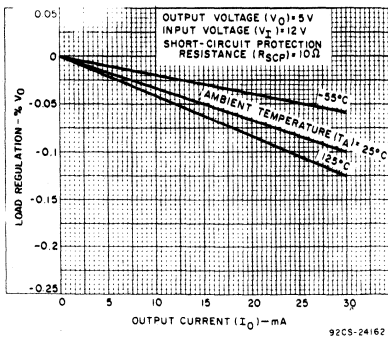


Fig. 7 - Load regulation with current limiting.

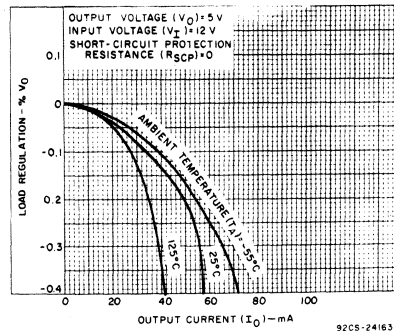


Fig. 8 - Load regulation with current limiting.

Linear Integrated Circuits

CA723, CA723C Types

TYPICAL CHARACTERISTICS CURVES FOR TYPE CA723 (Cont'd)

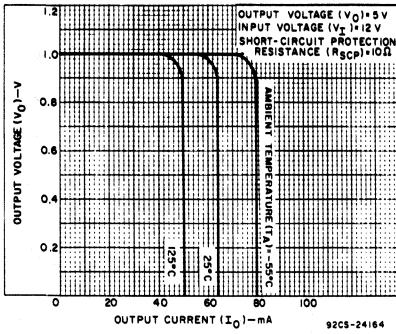


Fig. 9 - Current limiting characteristics.

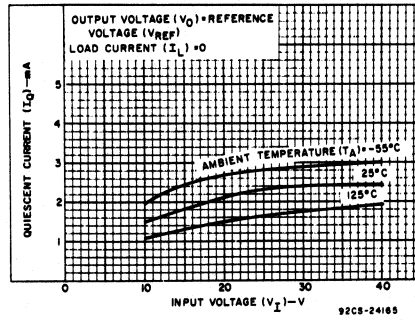


Fig. 10 - Quiescent current vs. input voltage.

TYPICAL CHARACTERISTICS CURVES FOR TYPE CA723C

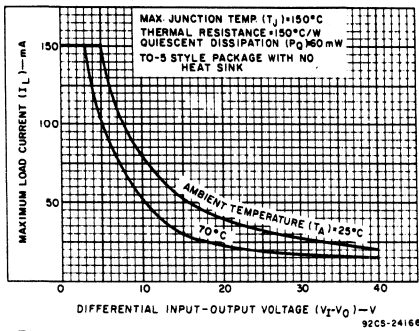


Fig. 11 - Max. load current vs differential input-output voltage CA723CT.

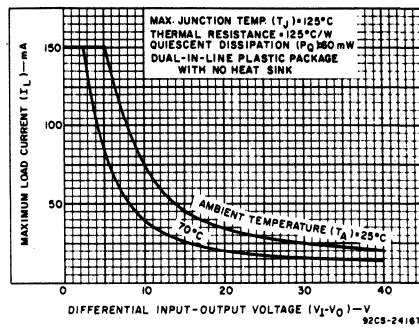


Fig. 12 - Max. load current vs differential input-output voltage for CA723CE.

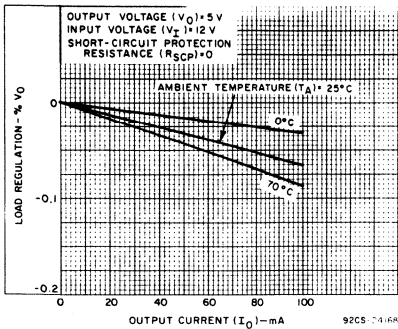


Fig. 13 - Load regulation without current limiting.

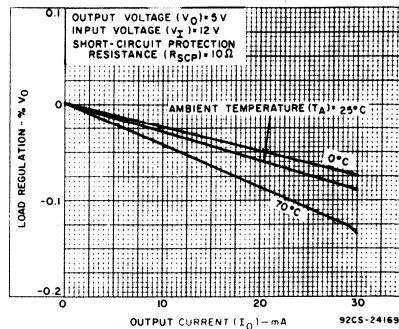


Fig. 14 - Load regulation with current limiting.

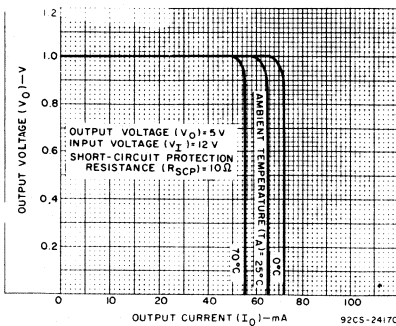


Fig. 15 - Current limiting characteristics.

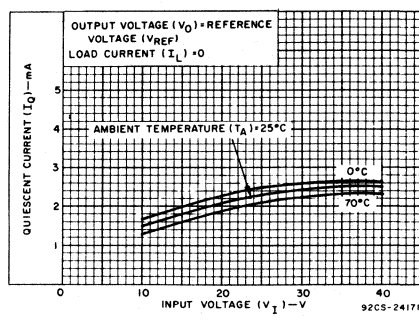


Fig. 16 - Quiescent current vs. input voltage.

Power Control Circuits

CA723, CA723C Types

TYPICAL CHARACTERISTICS CURVES FOR TYPES CA723 AND CA723C

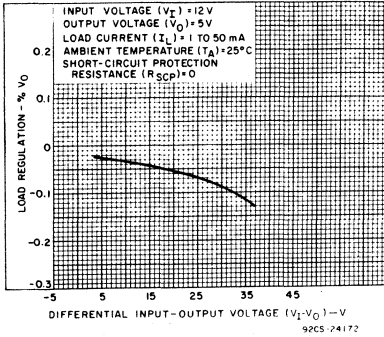


Fig. 17 - Load regulation vs. differential input-output voltage.

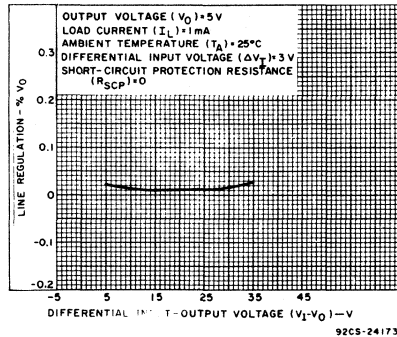


Fig. 18 - Line regulation vs. differential input-output voltage.

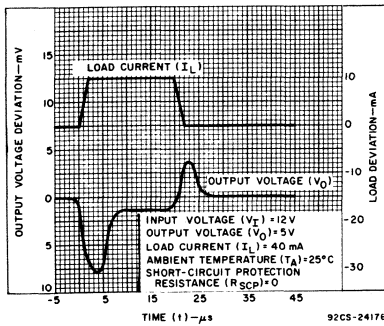


Fig. 19 - Line transient response.

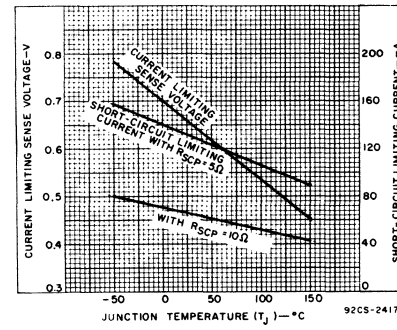


Fig. 20 - Current limiting characteristics vs. junction temperature.

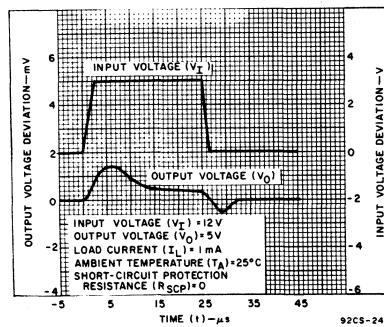


Fig. 21 - Load transient response.

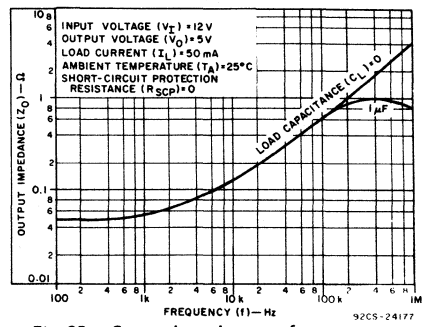
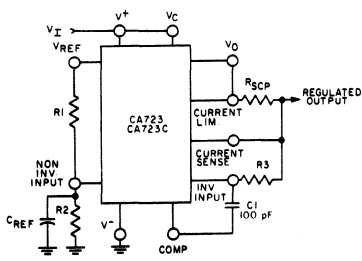


Fig. 22 - Output impedance vs. frequency.

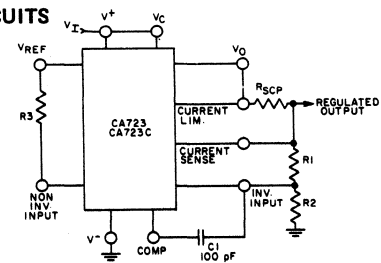
TYPICAL APPLICATION CIRCUITS



CIRCUIT PERFORMANCE DATA:
 REGULATED OUTPUT VOLTAGE . . . 5 V
 LINE REGULATION ($\Delta V_1 = 3$ V) . . . 1.5 mV
 LOAD REGULATION ($\Delta I_L = 50$ mA) . . . 4.5 mV

Note: $R_3 = \frac{R_1 R_2}{R_1 + R_2}$ for minimum temperature drift

Fig. 23 - Low-voltage regulator circuit ($V_O = 2$ to 7 volts).



CIRCUIT PERFORMANCE DATA:
 REGULATED OUTPUT VOLTAGE . . . 15 V
 LINE REGULATION ($\Delta V_1 = 3$ V) . . . 1.5 mV
 LOAD REGULATION ($\Delta I_L = 50$ mA) . . . 4.5 mV

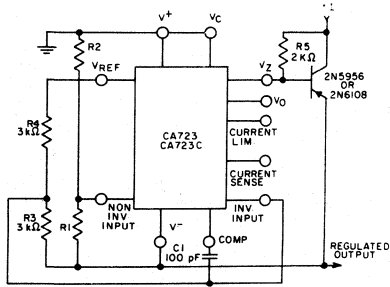
Note: $R_3 = \frac{R_1 R_2}{R_1 + R_2}$ for minimum temperature drift

Fig. 24 - High-voltage regulator circuit ($V_O = 7$ to 37 volts).

Power Control Circuits

CA723, CA723C Types

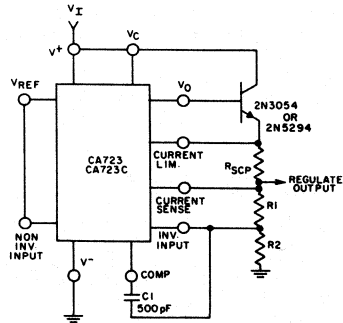
TYPICAL APPLICATION CIRCUITS (Cont'd)



CIRCUIT PERFORMANCE DATA:
 REGULATED OUTPUT VOLTAGE . . . -15 V
 LINE REGULATION ($\Delta V_I = 3$ V) . . . 1 mV
 LOAD REGULATION ($\Delta I_L = 100$ mA) . . . 2 mV
 Note: For applications employing the TO-5 style package and where V_Z is required, an external 6.2-volt zener diode should be connected in series with V_O (Terminal 6).

92CS-24180R1

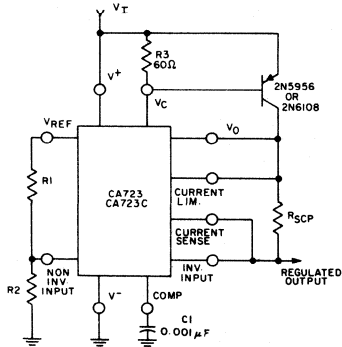
Fig. 25 - Negative-voltage regulator circuit.



CIRCUIT PERFORMANCE DATA:
 REGULATED OUTPUT VOLTAGE . . . 15 V
 LINE REGULATION ($\Delta V_I = 3$ V) . . . 1.5 mV
 LOAD REGULATION ($\Delta I_L = 1$ A) . . . 15 mV

92CS-24181R1

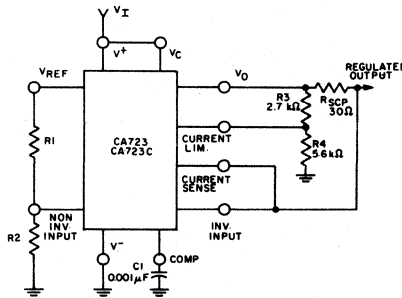
Fig. 26 - Positive-voltage-regulator circuit (with external n-p-n pass transistor).



CIRCUIT PERFORMANCE DATA:
 REGULATED OUTPUT VOLTAGE . . . 5 V
 LINE REGULATION ($\Delta V_I = 3$ V) . . . 0.5 mV
 LOAD REGULATION ($\Delta I_L = 1$ A) . . . 5 mV

92CS-24182R1

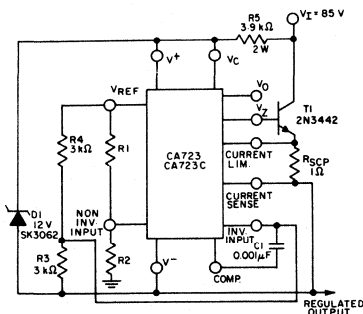
Fig. 27 - Positive voltage-regulator circuit (with external p-n-p pass transistor).



CIRCUIT PERFORMANCE DATA:
 REGULATED OUTPUT VOLTAGE . . . 5 V
 LINE REGULATION ($\Delta V_I = 3$ V) . . . 0.5 mV
 LOAD REGULATION ($\Delta I_L = 10$ mA) . . . 1 mV
 SHORT-CIRCUIT CURRENT . . . 20 mA

92CS-24183

Fig. 28 - Foldback current-limiting circuit.

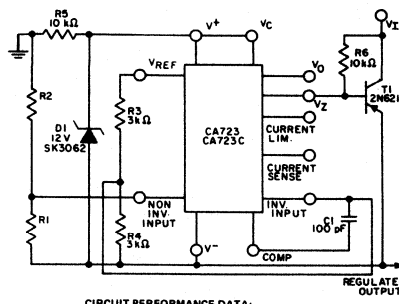


Note: For applications employing the TO-5 style package and where V_Z is required, an external 6.2-volt zener diode should be connected in series with V_O (Terminal 6).

CIRCUIT PERFORMANCE DATA:
 REGULATED OUTPUT VOLTAGE . . . 50 V
 LINE REGULATION ($\Delta V_I = 20$ V) . . . 15 mV
 LOAD REGULATION ($\Delta I_L = 50$ mA) . . . 20 mV

92CS-24184

Fig. 29 - Positive-floating regulator circuit.



CIRCUIT PERFORMANCE DATA:
 REGULATED OUTPUT VOLTAGE . . . -100 V
 LINE REGULATION ($\Delta V_I = 20$ V) . . . 30 mV
 LOAD REGULATION ($\Delta I_L = 100$ mA) . . . 20 mV

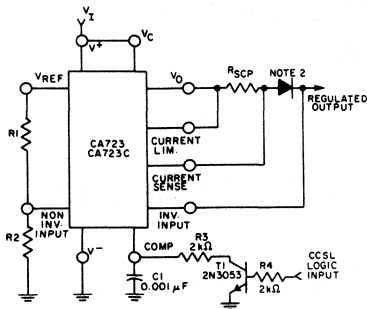
Note: For applications employing the TO-5 style package and where V_Z is required, an external 6.2-volt zener diode should be connected in series with V_O (Terminal 6).

92CS-24185

Fig. 30 - Negative-floating regulator circuit.

Power Control Circuits CA723, CA723C Types

TYPICAL APPLICATION CIRCUITS (Cont'd)

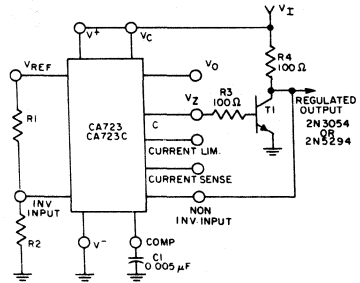


CIRCUIT PERFORMANCE DATA:
 REGULATED OUTPUT VOLTAGE 5 V
 LINE REGULATION ($\Delta V_I = 3$ V) 0.5 mV
 LOAD REGULATION ($\Delta I_L = 50$ mA) 1.5 mV

Note 1: A current limiting transistor may be used for shutdown if current limiting is not required.
Note 2: Add a diode if $V_O > 10$ V.

92CS-24186R1

Fig. 31 — Remote shutdown regulator circuit with current limiting.



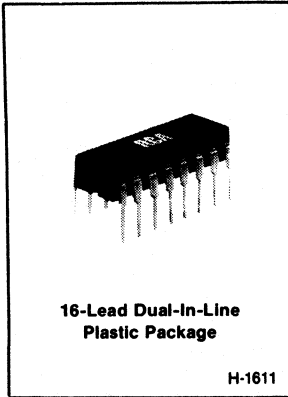
CIRCUIT PERFORMANCE DATA:
 REGULATED OUTPUT VOLTAGE 5 V
 LINE REGULATION ($\Delta V_I = 10$ V) 0.5 mV
 LOAD REGULATION ($\Delta I_L = 100$ mA) 1.5 mV

Note: For applications employing the TO-5 style package and where V_Z is required, an external 6.2-volt zener diode should be connected in series with V_O (Terminal 6).

92CS-24187R1

Fig. 32 — Shunt regulator circuit.

CA1524, CA2524, CA3524 Types



Regulating Pulse Width Modulator

Features:

- Complete PWM power control circuitry
- Separate outputs for Single-ended or push-pull operation
- Line and load regulation of 0.2% typ.
- Internal reference supply with 1% max. oscillator and reference voltage variation over full temperature range
- Standby current of less than 10 mA
- Frequency of operation beyond 100 kHz

The RCA-CA1524, CA2524, and CA3524 are silicon monolithic integrated circuits designed to provide all the control circuitry for use in a broad range of switching regulator circuits.

The CA1524, CA2524, and CA3524 have all the features of the industry types SG1524, SG2524, and SG3524 respectively. A block diagram of the CA1524 Series is shown in Fig. 1. The circuit includes a zener voltage reference, transconductance error amplifier, precision R-C oscillator, pulse-width modulator, pulse-steering flip-flop, dual alternating output switches, and current-limiting and shutdown circuitry. This device can be used for switching regulators of either polarity, transformer-coupled dc-dc converters, transformerless voltage doublers, dc-ac power inverters, highly efficient variable power supplies, and polarity converters, as well as other power-control applications.

The CA1524 is specified for the military temperature range of -55°C to +125°C.

- Variable output dead time of 0.5 to 5 μ s
- Low $V_{CE(sat)}$ over the temperature range

Applications:

- Positive and negative regulated supplies
- Dual-output regulators
- Flyback converters
- DC-DC transformer-coupled regulating converters
- Single-ended DC-DC converters
- Variable power supplies

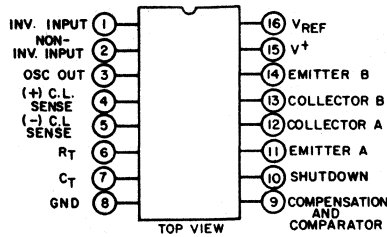
The CA2524 and CA3524 are specified for the commercial temperature range of 0°C to 70°C. All types operate over a supply voltage range of 8 to 40 V, have a rated operating temperature range of -55°C to +125°C, and are supplied in 16-lead dual-in-line plastic packages (E suffix). The CA3524 is available in chip form (H suffix).

MAXIMUM RATINGS, Absolute-Maximum Values:

INPUT VOLTAGE (BETWEEN V_{IN} AND GROUND TERMINALS)	40 V
OPERATING VOLTAGE RANGE (V_{IN} TO GROUND)	8 to 40 V
OUTPUT CURRENT EACH OUTPUT: (TERMINALS 11,12 or 13,14)	100 mA
OUTPUT CURRENT (REFERENCE REGULATOR)	50 mA
OSCILLATOR CHARGING CURRENT	5 mA
DEVICE DISSIPATION:	
Up to $T_A = 25^\circ\text{C}$	1 W
Above $T_A = 25^\circ\text{C}$	Derate linearly 8 mW/ $^\circ\text{C}$
OPERATING TEMPERATURE RANGE	-55 to +125 $^\circ\text{C}$
STORAGE TEMPERATURE RANGE	-65 to +150 $^\circ\text{C}$

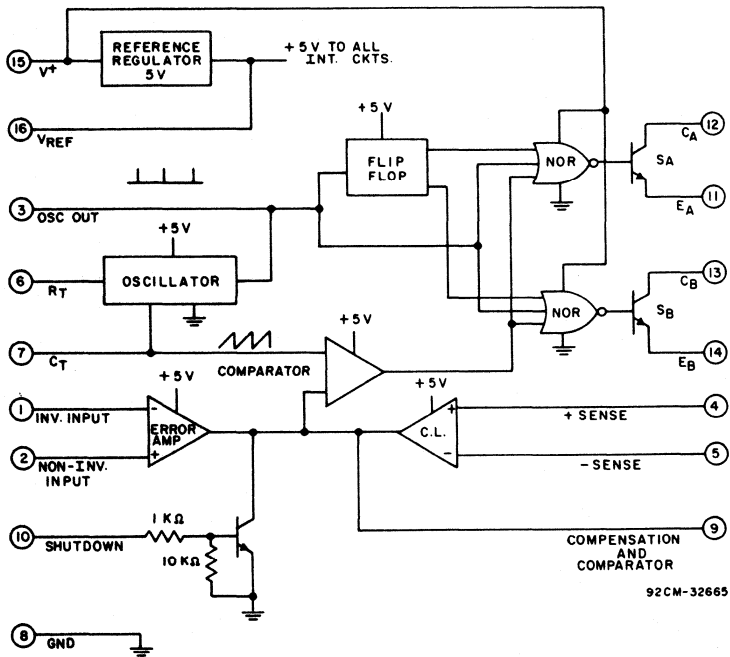
Power Control Circuits

CA1524, CA2524, CA3524 Types



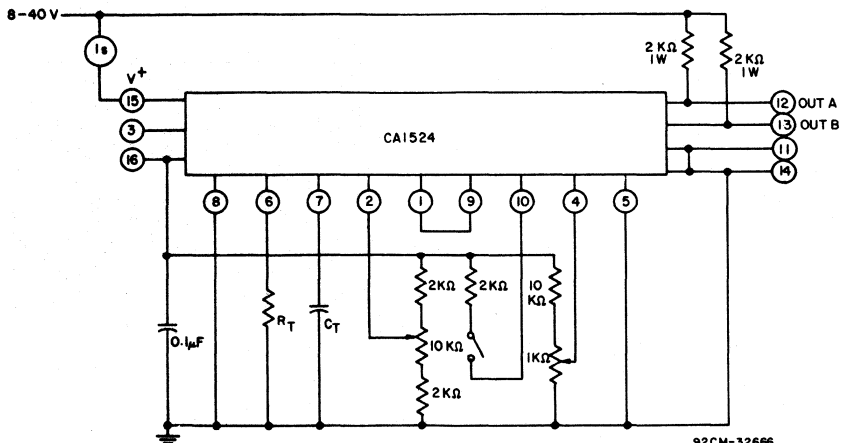
92CS-32664R1

TOP VIEW TERMINAL ASSIGNMENT



92CM-32665

Fig. 1-Functional block diagram of CA1524 series.



92CM-32666

Fig. 2-Open loop test circuit for CA1524 series.

Linear Integrated Circuits

CA1524, CA2524, CA3524 Types

CIRCUIT DESCRIPTION

Voltage Reference Section (see Fig. 3).

The CA1524 Series contains an internal series voltage regulator employing a zener reference to provide a nominal 5 volts output, which is used to bias all internal timing and control circuitry. The output of this regulator is available at terminal 16 and is capable of supplying up to 50 mA. output current. For higher currents, the circuit of Fig. 3 may be used with an external p-n-p transistor and bias resistor. The internal regulator may be bypassed for operation from a fixed 5 volt supply by connecting both terminals 15 and 16 to the input voltage, which must not exceed 6 volts.

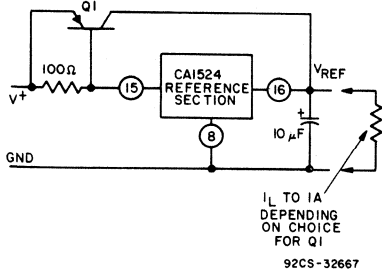


Fig. 3—Circuit for expanding the reference current capability.

Fig. 4 shows the temperature variation of the reference voltage with supply

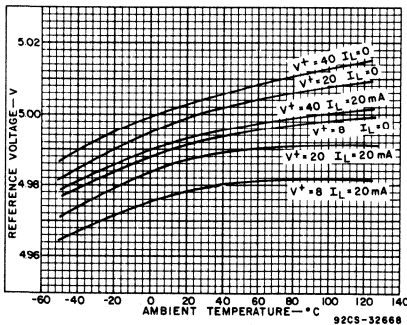


Fig. 4—Typical reference voltage as a function of ambient temperature.

voltages of 8 to 40 volts and load currents up to 20 mA. Load regulation and line regulation curves are shown in Figs. 5 and 6, respectively.

Oscillator Section (see Fig. 3)

Transistors Q42, Q43 and Q44, in conjunction with an external resistor R_T , establishes a constant charging current into an external capacitor C_T to provide a linear ramp voltage at terminal 7. The ramp voltage has a value that ranges from 0.6 to 3.5 volts and is used as the reference for the comparator in the device. The charging current is equal to $(5 - 2V_{BE})/R_T$ or approximately $3.6/R_T$ and should be kept within the range of 30

μA to 2 mA by varying R_T . The discharge time of C_T determines the pulse width of the oscillator output pulse at terminal 3. This pulse has a practical range of 0.5 μs to 5 μs for a capacitor range of 0.001 to 0.1 μF . The pulse has two internal uses: as a dead-time control or blanking pulse to the output stages to assure that both outputs

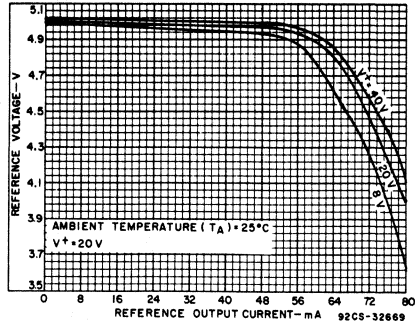


Fig. 5—Typical reference voltage as a function of reference output current.

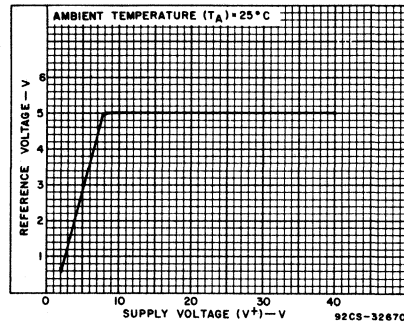


Fig. 6—Typical reference voltage as a function of supply voltage.

cannot be on simultaneously and as a trigger pulse to the internal flip-flop which controls the switching of the output between the two output channels. The output dead-time relationship is shown in Fig. 7. Pulse widths less than 0.5 μs may allow false triggering of one output by removing the blanking pulse prior to a stable state in the flip-flop.

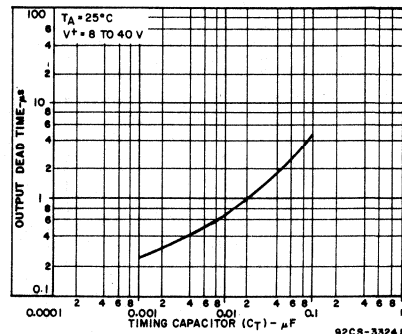


Fig. 7—Typical output stage dead time as a function of timing capacitor value.

Power Control Circuits

CA1524, CA2524, CA3524 Types

ELECTRICAL CHARACTERISTICS at $T_A = -55$ to $+125^\circ\text{C}$ for CA1524,
 0 to $+70^\circ\text{C}$ for the CA2524 and CA3524; $V^+ = 20\text{ V}$ and $f = 20\text{ kHz}$,
 unless otherwise stated.

CHARACTERISTIC	TEST CONDITIONS	LIMITS						UNITS
		CA1524, CA2524			CA3524			
		Min.	Typ.	Max.	Min.	Typ.	Max.	
Reference Section:								
Output Voltage:		4.8	5.0	5.2	4.6	5.0	5.4	V
Line Regulation	$V^+ = 8$ to 40 Volts	—	10	20	—	10	30	mV
Load Regulation	$I_L = 0$ to 20 mA	—	20	50	—	20	50	mV
Ripple Rejection	$f = 120\text{Hz}$, $T_A = 25^\circ\text{C}$	—	66	—	—	66	—	dB
Short Circuit Current Limit	$V_{REF} = 0$, $T_A = 25^\circ\text{C}$	—	100	—	—	100	—	mA
Temperature Stability	Over Operating Temperature Range	—	0.3	1	—	0.3	1	%
Long Term Stability	$T_A = 25^\circ\text{C}$	—	20	—	—	20	—	mV/chr
Oscillator Section:								
Maximum Frequency	$C_T = 0.001\ \mu\text{F}$ $R_T = 2\ \text{K}\Omega$	—	300	—	—	300	—	kHz
Initial Accuracy	R_T and C_T constant	—	5	—	—	5	—	%
Voltage Stability	$V^+ = 8$ to 40 Volts, $T_A = 25^\circ\text{C}$	—	—	1	—	—	1	%
Temperature Stability	Over Operating Temperature Range	—	—	2	—	—	2	%
Output Amplitude	Term.3, $T_A = 25^\circ\text{C}$	—	3.5	—	—	3.5	—	V
Output Pulse Width	$C_T = 0.01\ \mu\text{F}$ $T_A = 25^\circ\text{C}$	—	0.5	—	—	0.5	—	μs
Error Amplifier Section:								
Input Offset Voltage	$V_{CM} = 2.5$ Volts	—	0.5	5	—	2	10	mV
Input Bias Current	$V_{CM} = 2.5$ Volts	—	1	10	—	1	10	μA
Open Loop Voltage Gain		72	80	—	60	80	—	dB
Common Mode Voltage	$T_A = 25^\circ\text{C}$	1.8	—	3.4	1.8	—	3.4	V
Common Mode Rejection Ratio	$T_A = 25^\circ\text{C}$	—	70	—	—	70	—	dB
Small Signal Bandwidth	$A_V = 0\text{dB}$, $T_A = 25^\circ\text{C}$	—	3	—	—	3	—	MHz
Output Voltage	$T_A = 25^\circ\text{C}$	0.5	—	3.8	0.5	—	3.8	V

If a small value of C_T must be used, the pulse width can be further expanded by the addition of a shunt capacitor in the order of $100\ \text{pF}$ but no greater than $1000\ \text{pF}$, from terminal 3 to ground. When the oscillator output pulse is used as a sync input to an oscilloscope, the cable and input capacitances may increase the pulse width slightly. A $2\ \text{k}\Omega$ resistor at terminal 3 will usually provide sufficient decoupling of the cable. The upper limit of the pulse width is determined by the maximum duty cycle acceptable. To provide an expansion of the dead time without loading the oscillator, the circuit of Fig. 8 may be used.

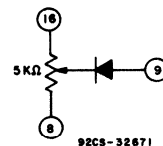


Fig. 8—Circuit for expansion of dead time.

The oscillator period is determined by R_T and C_T , with an approximate value of $t = R_T C_T$, where R_T is in ohms, C_T is in μF , and t is in μs . Excess lead lengths, which produce stray capacitances, should be avoided in connecting R_T and

Linear Integrated Circuits

CA1524, CA2524, CA3524 Types

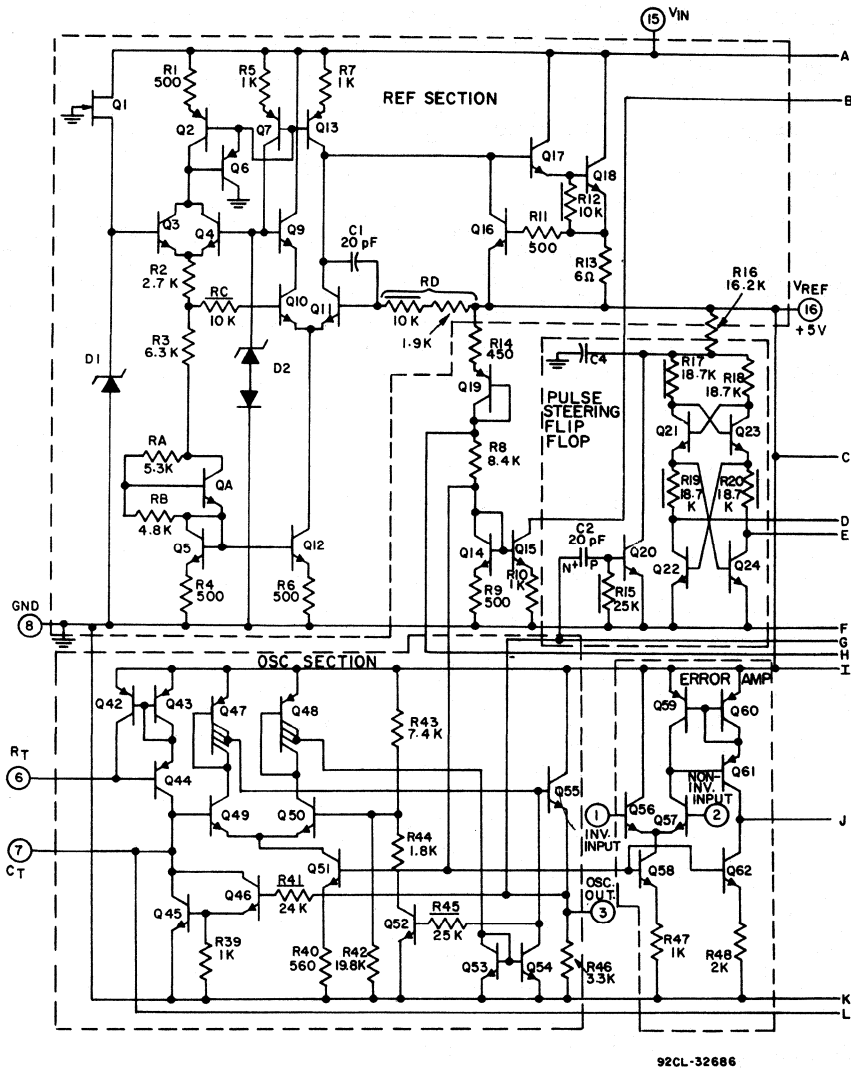


Fig. 9-Schematic diagram (continued on next page).

Power Control Circuits
CA1524, CA2524, CA3524 Types

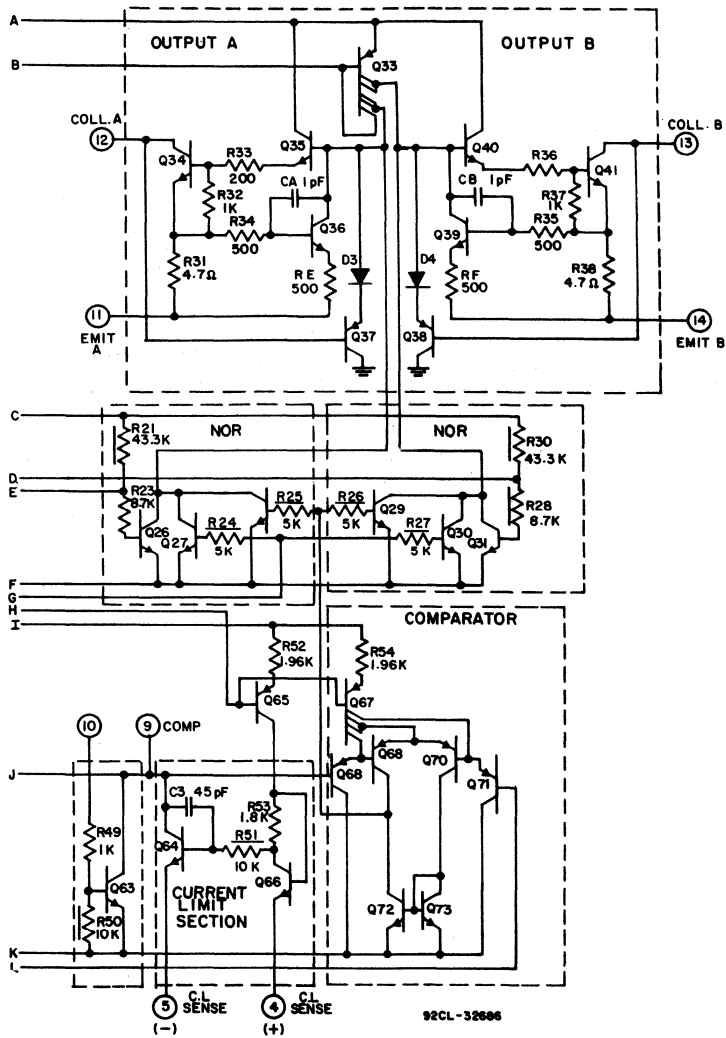


Fig. 9-Schematic diagram (continued from previous page).

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ELECTRICAL CHARACTERISTICS at $T_A = -55$ to $+125^\circ\text{C}$ for CA1524, 0 to $+70^\circ\text{C}$ for the CA2524 and CA3524; $V^+ = 20\text{ V}$ and $f = 20\text{ kHz}$, unless otherwise stated.

CHARACTERISTIC	TEST CONDITIONS	LIMITS						UNITS
		CA1524, CA2524			CA3524			
		Min.	Typ.	Max.	Min.	Typ.	Max.	
Comparator Section:								
Duty Cycle	% Each Output On	0	—	45	0	—	45	%
Input Threshold	Zero Duty Cycle	—	1	—	—	1	—	V
Input Threshold	Max. Duty Cycle	—	3.5	—	—	3.5	—	V
Input Bias Current		—	1	—	—	1	—	μA
Current Limiting Section:								
Sense Voltage	Term. 9 = 2 V with Error Amplifier Set for Max Out, $T_A = 25^\circ\text{C}$	190	200	210	180	200	220	mV
Sense Voltage T.C.		—	0.2	—	—	0.2	—	$\text{mV}/^\circ\text{C}$
Common Mode Voltage		-1	—	+1	-1	—	+1	V
Output Section: (Each Output)								
Collector-Emitter Voltage		40	—	—	40	—	—	V
Collector Leakage Current	$V_{CE} = 40\text{ V}$	—	0.1	50	—	0.1	50	μA
Saturation Voltage	$V^+ = 40\text{ V}$, $I_C = 50\text{ mA}$	—	0.8	2	—	0.8	2	V
Emitter Output Voltage	$V^+ = 20\text{ V}$	17	18	—	17	18	—	V
Rise Time	$R_C = 2\text{ K}\Omega$, $T_A = 25^\circ\text{C}$	—	0.2	—	—	0.2	—	μs
Fall Time	$R_C = 2\text{ K}\Omega$, $T_A = 25^\circ\text{C}$	—	0.1	—	—	0.1	—	μs
Total Standby Current: *Is	$V^+ = 40\text{ V}$	—	4	10	—	4	10	mA

* Excluding oscillator charging current, error and current limit dividers, and with outputs open.

C_T to their respective terminals. Fig. 10 provides curves for selecting these values for a wide range of oscillator periods. For series regulator applications, the two outputs can be connected in parallel for an effective 0-90% duty cycle with the output stage frequency the same as the oscillator frequency. Since the outputs are separate, push-pull and flyback applications are possible. The flip-flop divides the frequency such that the duty cycle of each output is 0-45% and the overall frequency is half that of the oscillator. Curves of the output duty cycle as a function of the voltage at terminal 9 are shown in Fig. 11. To synchronize two or more CA1524's, one must be designated as master, with $R_T C_T$ set for the correct period. Each of the remaining units (slaves) must have a C_T of 1/2 the value used in the master and approximately a 10% longer $R_T C_T$ period than the master. Connecting terminal 3

together on all units assures that the master output pulse, which occurs first and has a wider pulse width, will reset the slave units.

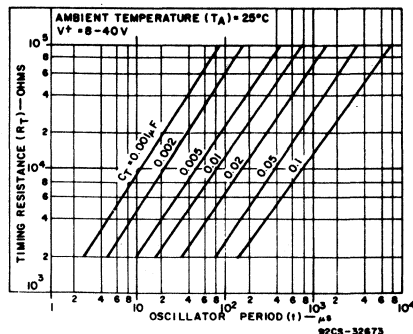


Fig. 10—Typical oscillator period as a function of R_T and C_T .

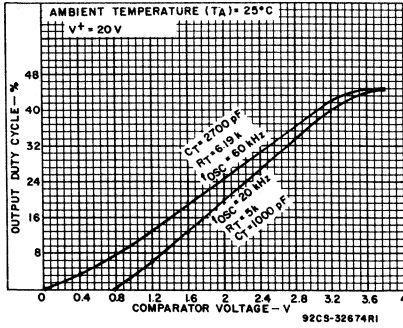


Fig. 11—Typical duty cycle as a function of comparator voltage (at terminal 9).

Error Amplifier Section (see Fig. 9)

The error amplifier consists of a differential pair (Q56, Q57) with an active load (Q61 and Q62) forming a differential transconductance amplifier. Since Q61 is driven by a constant current source, Q62, the output impedance R_{out} , terminal 9, is very high ($\approx 5 \text{ M}\Omega$).

The gain is:

$$A_v = g_m R = 8 I_c R / 2KT = 10^4,$$

$$R_{out} R_L$$

where $R = \frac{R_{out} R_L}{R_{out} + R_L}$, $R_L = \infty$, $A_v \approx 10^4$

Since R_{out} is extremely high, the gain can be easily reduced from a nominal 104 (80 dB) by the addition of an external shunt resistor from terminal 9 to ground as shown in Fig. 12.

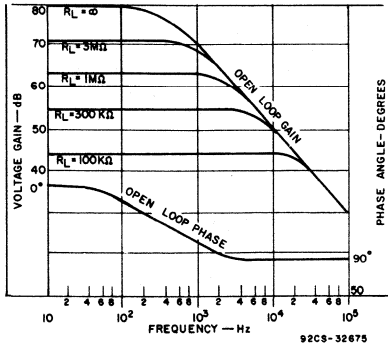


Fig. 12—Open-loop error amplifier response characteristics.

The output amplifier terminal is also used to compensate the system for ac stability. The frequency response and phase shift curves are shown in Fig. 12. The uncompensated amplifier has a single pole at approximately 250 Hz and a unity gain cross-over at 3 MHz.

Since most output filter designs introduce one or more additional poles at a lower frequency, the best network to stabilize the system is a series RC combination at terminal 9 to ground. This net-

work should be designed to introduce a zero to cancel out one of the output filter poles. A good starting point to determine the external poles is a 1000 pF capacitor and a variable series 50 kΩ potentiometer from terminal 9 to ground. The compensation point is also a convenient place to insert any programming signal to override the error amplifier. Internal shutdown and current limiting are also connected at terminal 9. Any external circuit that can sink 200 μA can pull this point to ground and shut off both output drivers.

While feedback is normally applied around the entire regulator, the error amplifier can be used with conventional operational amplifier feedback and will be stable in either the inverting or non-inverting mode. Input common-mode limits must be observed; if not, output signal inversion may result. The internal 5-volt reference can be used for conventional regulator applications if divided as shown in Fig. 13. If the error amplifier is connected as a unity gain amplifier, a fixed duty cycle application results.

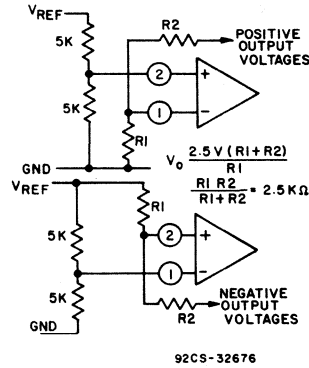


Fig. 13—Error amplifier biasing circuits.

Current Limiting Section (see Fig. 9)

The current limiting section consists of two transistors (Q64, Q66) connected to the error amplifier output terminal. By matching the base-to-emitter voltages of Q64 and Q66 and assuming negligible voltage drop across R_{51} :

$$V_{THRESHOLD} = V_{BE}(Q64) + I(Q65) R_{53} - V_{BE}(Q66)$$

$$= I(Q65) R_{53} \approx 200 \text{ mV}$$

Although this circuit provides a small threshold with a negligible temperature coefficient, some limitations to its use must be considered. The circuit has a ± 1 volt common mode range which requires sensing in the ground line. The other factor to consider is that the frequency compensation provided by $R_{51}C_3$ and Q64 produces a roll-off pole at approximately 300 Hz.

CA1524, CA2524, CA3524 Types

Due to the low gain of this circuit, there is a transition region as the current-limit amplifier takes over pulse width control from the error amplifier. For testing purposes, the threshold is defined as the input voltage to the current-limiting amplifier to get 25% duty cycle with the error amplifier signaling maximum duty cycle.

In addition to constant current limiting, terminals 4 and 5 may also be used in transformer-coupled circuits to sense primary current and shorten an output pulse, should transformer saturation occur (see Fig. 23). Another application is to ground terminal 5 and use terminal 4 as an additional shutdown terminal: i.e. the output will be off with terminal 4 open and on when it is grounded. Finally, foldback current limiting can be provided with the network of Fig. 14. This circuit can reduce the short-circuit current (I_{SC}) to approximately 1/3 the maximum available output current (I_{MAX}).

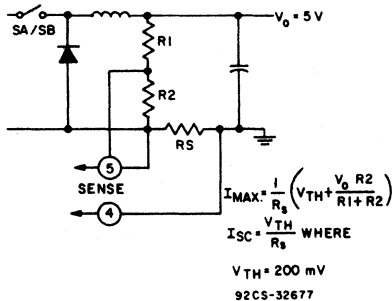


Fig. 14—Foldback current limiting circuit used to reduce power dissipation under shorted output conditions.

Output Section (see Fig. 9)

The CA1524 Series outputs are two identical n-p-n transistors with both collectors and emitters uncommitted. Each output transistor has antisaturation circuitry that enables a fast transient response for the wide range of oscillator frequencies. Current limiting of the output section is set at 100 mA for each output and 100 mA total if both outputs are paralleled. Having both emitters and collector available provides the versatility to drive either n-p-n or p-n-p external transistors. Curves of the output saturation voltage as a function of temperature and output current are shown in Figs. 15 and 16 respectively.

There are a number of output configurations possible in the application of the CA1524 to voltage regulator circuits which fall into three basic classifications:

1. Capacitor-diode coupled voltage multipliers
2. Inductor-capacitor single-ended circuits
3. Transformer-coupled circuits

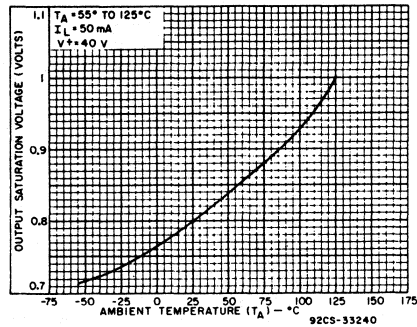


Fig. 15—Typical output saturation voltage as function of ambient temperature.

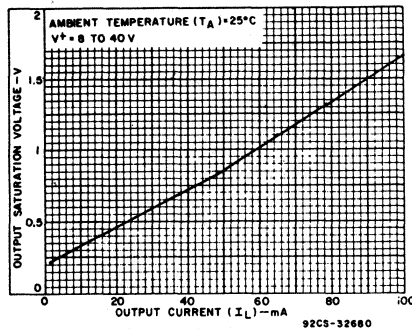


Fig. 16—Typical output saturation voltage as a function of output current.

Examples of these configurations are shown in Fig. 17, 18, and 19. In each case, the switches can be either the output transistors in the CA1524 or added external transistors, depending on the load current requirements.

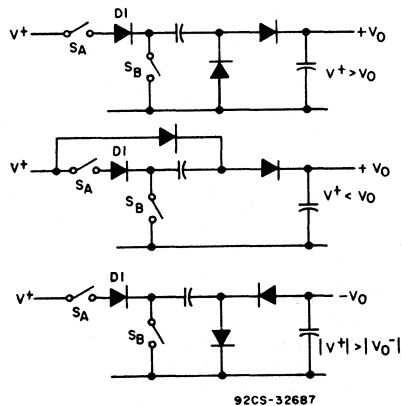


Fig. 17—Capacitor-diode coupled voltage multiplier output stages. (Note: Diode D1 is necessary to prevent reverse emitter-base breakdown of transistor switch SA).

CA1524, CA2524, CA3524 Types

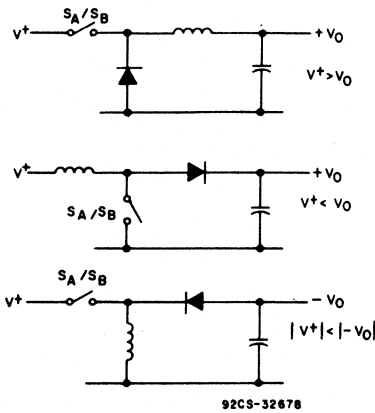


Fig. 18—Single-ended inductor circuits where the two outputs of the 1524 are connected in parallel.

TABLE I - Input vs. Output voltage, and Feedback Resistor Values for $I_L = 40 \text{ mA}$. (For capacitor-diode output circuit in Fig. 20)

V_O (V)	R_2 (k Ω)	V^+ (min.) (V)
-0.5	6	8
-2.5	10	9
-3	11	10
-4	13	11
-5	15	12
-6	17	13
-7	19	14
-8	21	15
-9	23	16
-10	25	17
-11	27	18
-12	29	19
-13	31	20
-14	33	21
-15	35	22
-16	37	23
-17	39	24
-18	41	25
-19	43	26
-20	45	27

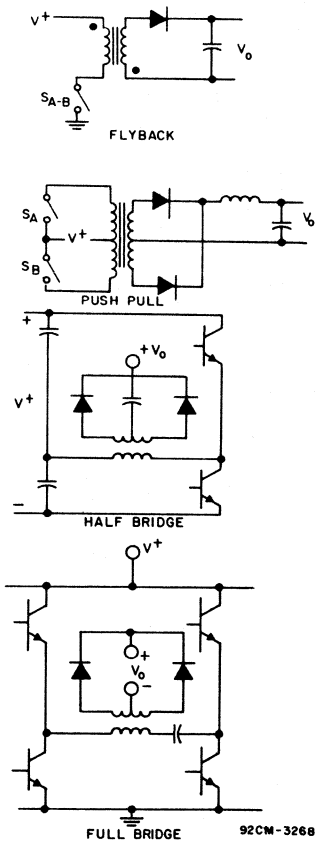


Fig. 19—Transformer-coupled outputs.

APPLICATIONS

Capacitor-Diode Output Circuit

A capacitor-diode output filter is used in Fig. 20 to convert +15 Vdc to -5 Vdc at output currents up to 50 mA. Since the output transistors have built-in current limiting, no additional current limiting is needed. Table I gives the required minimum input voltage and feedback resistor values, R_2 , for an output voltage

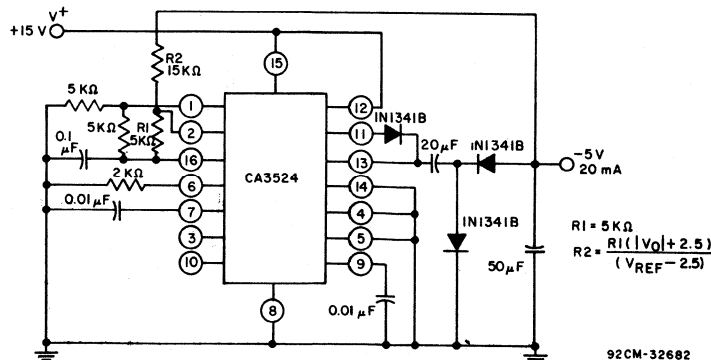


Fig. 20—Capacitor-diode output circuit.

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range of -0.5 V to -20 V with an output current of 40 mA .

Single-Ended Switching Regulator

The CA1524 in the circuit of Fig. 21 has both output stages connected in parallel to produce an effective 0-90% duty cycle. Transistor Q1 is pulsed on and off by these output stages. Regulation is achieved from the feedback provided by R1 and R2 to the error amplifier which adjusts the on-time of the output transistors according to the load current being drawn. Various output voltages can be obtained by adjusting R1 and R2. The use of an output inductor requires an R-C phase compensation network to stabilize the system. Current limiting is set at 1.9 amperes by the sense resistor R3.

Flyback Converter

Fig. 22 shows a flyback converter circuit for generating a dual 15-volt output at 20 mA from a 5-volt regulated line. Reference voltage is provided by the input and the internal reference generator is unused. Current limiting in this circuit is accomplished by sensing current in the primary line and resetting the soft-start circuit.

Push-Pull Converter

The output stages of the CA1524 provide the drive for transistors Q1 and Q2 in the push-pull application of Fig. 23. Since the internal flip-flop divides the oscillator frequency by two, the oscillator must be set at twice the output frequency. Current limiting for this circuit is done in the primary of transformer T1 so that the pulse width will be reduced if transformer saturation should occur.

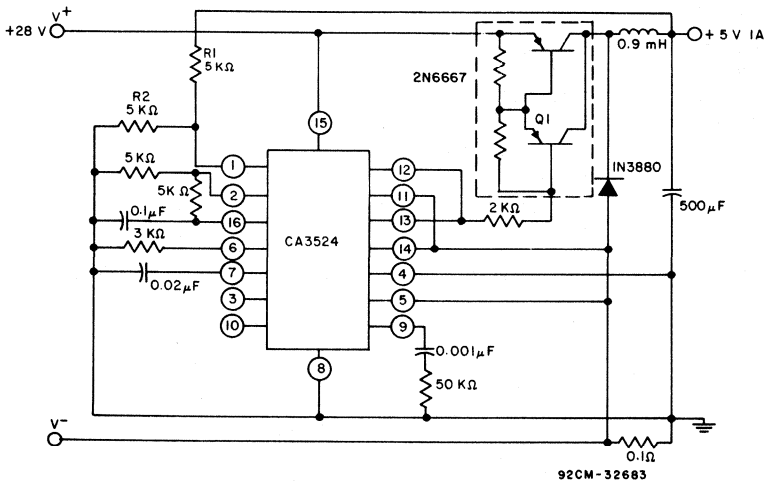


Fig. 21—Single-ended LC switching regulator circuit.

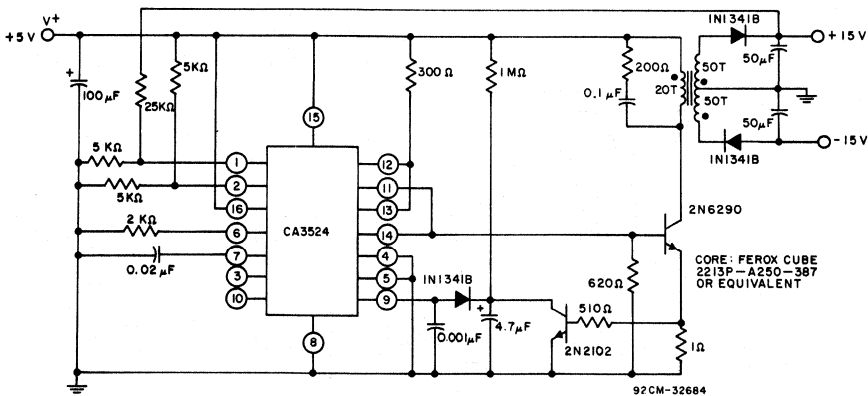


Fig. 22—Flyback converter circuit.

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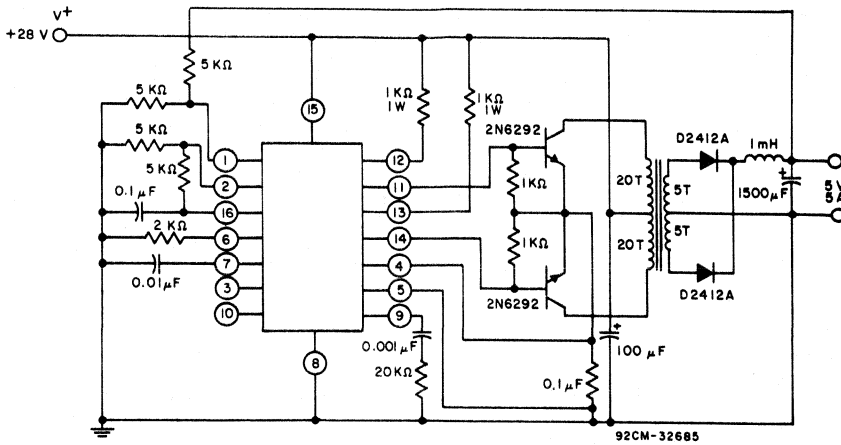


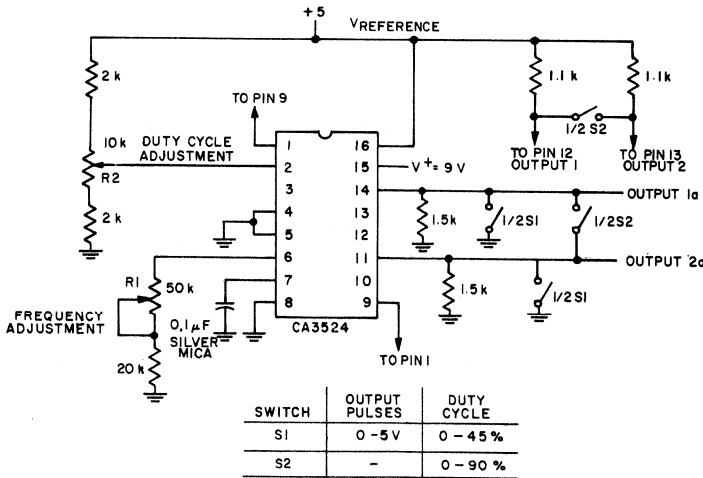
Fig. 23-Push-pull transformer-coupled converter.

Low-Frequency Pulse Generator

Fig. 24 shows the CA1524 being used as a low-frequency pulse generator. Since all components (error amplifier, oscillator, oscillator reference regulator, output transistor drivers) are on the IC, a regulated 5 V (or 2.5 V) pulse of 0%-45% (or 0%-90%) on time is possible over a frequency range of 150 to 500 Hz. Switch S₁ is used to go from a 5-V output pulse (S₁ closed) to a 2.5-V output pulse (S₁ open) with a duty cycle range of 0% to 45%. The output frequency will be roughly half of the oscillator frequency when the output transistors are not connected in parallel (75 Hz to 250 Hz respectively). Switch S₂ will allow both output stages to be paralleled for an effective duty cycle of 0%-90% with the output frequency range from 150 to 500 Hz. The frequency is adjusted by R₁; the duty cycle is controlled by R₂.

Efficient Laboratory Power Supply

The CA1524 as a highly-efficient laboratory supply is shown in Fig. 25. The output voltage can range from 7 to 30 volts for an input voltage range from 33 to 40 volts. Output current of up to 5 amperes is possible. The circuit operates as follows: The two output transistors of the CA1524 are connected in parallel to achieve a maximum duty cycle of 90%. They drive the 2N6650 p-n-p Darlington transistor. The error amplifier's input terminal, pin 1, is first adjusted to 3.4 volts through divider R₃, R₄ and R₅. R₄ is provided so the maximum output can be varied. For this application, the maximum output voltage is 30 volts. The internal reference level of the CA1524's reference regulator is varied, via R₇, over the amplifier's input span. This in turn varies the comparator voltage at pin 9 from a level of 0.5 to 3.8 volts, thus moving the



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Fig. 24-Low-frequency pulse generator.

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output section's on time. Since the reference level is varied, the feedback voltage will track that level and cause the output voltage to change respectively in track with the reference's change at pin 2. **Digital Readout Scale**

The CA1524 can be used as the driving source for an electronic scale application. The circuit shown in Figs. 26 and 27 uses half (Q_2) of the CA1524 output in a low-voltage switching regulator (2.2 V) application to drive the LED's displaying the weight. The remaining output stage (Q_1) is used as a driver for the sampling plates PL1 and PL2. Since the CA1524 contains a 5-volt internal regulator and a wide operating range of 8 to 40 volts, a single 9-volt battery can power the total system. The two plates, PL1 and PL2, are driven with opposite phase signals (frequency held constant but duty cycle may change) from the pulse-width

modulator IC (1524). The sensor, S, is located between the two plates. Plates PL1, S and PL2 form an effective capacitance bridge-type divider network. As plate S is moved according to the object's weight, a change in capacitance is noted between

PL1, S and PL2. This change is reflected as a voltage to the ac amplifier (CA3160). At the null position the signals from PL1 and PL2 as detected by S are equal in amplitude, but opposite in phase. As S is driven by the scale mechanism down toward PL2, the signal at S becomes greater. The CA3160 ac amplifier provides a buffer for the small signal change noted at S. The output of the CA3160 is converted to a dc voltage by a peak-to-peak detector. A peak-to-peak detector is needed, since the duty cycle of the sampled waveform is subject to change. The detector output is filtered further and displayed via the CA3161E and CA3162E digital readout system, indicating the weight on the scale.

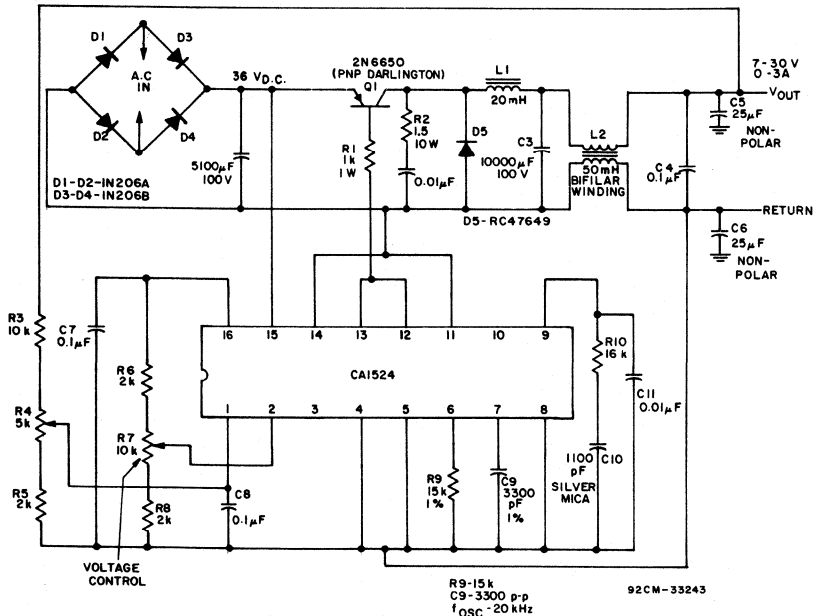


Fig. 25—The CA1524 used as a OA-5A, 7-30-V laboratory supply.

CA1524, CA2524, CA3524 Types

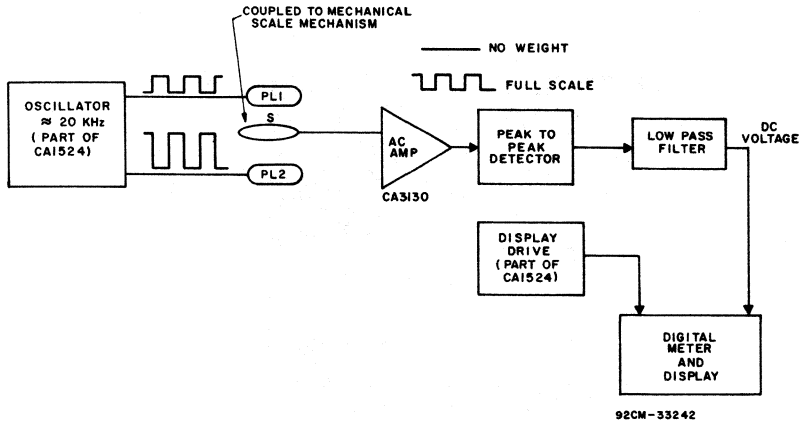


Fig. 26-Basic digital readout scale.

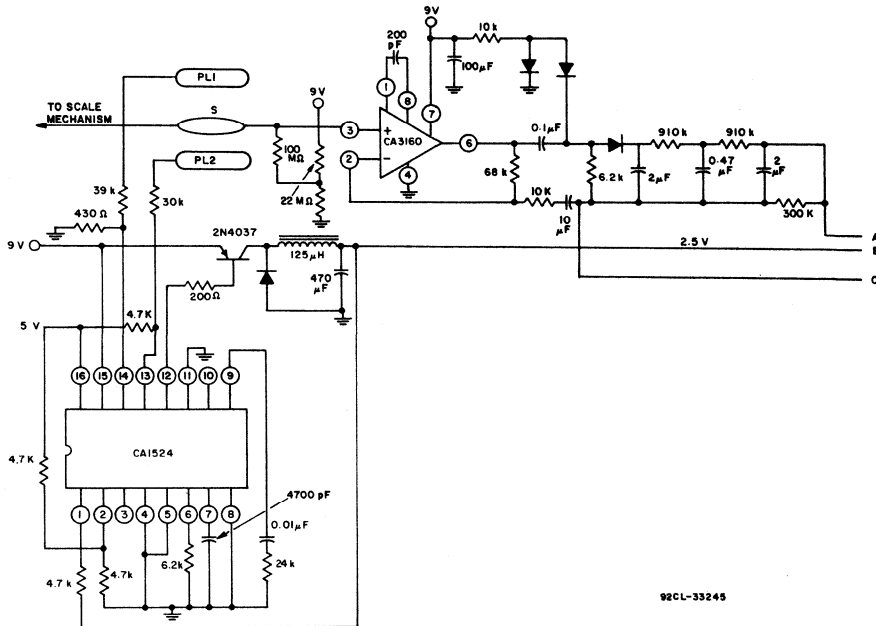
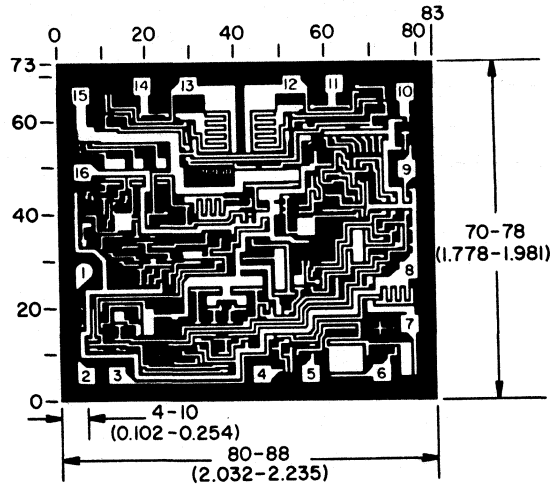


Fig. 27-Schematic diagram of digital readout scale.

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CA1524, CA2524, CA3524 Types



Dimensions and pad layout for CA3524H chip.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

The layout represents a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

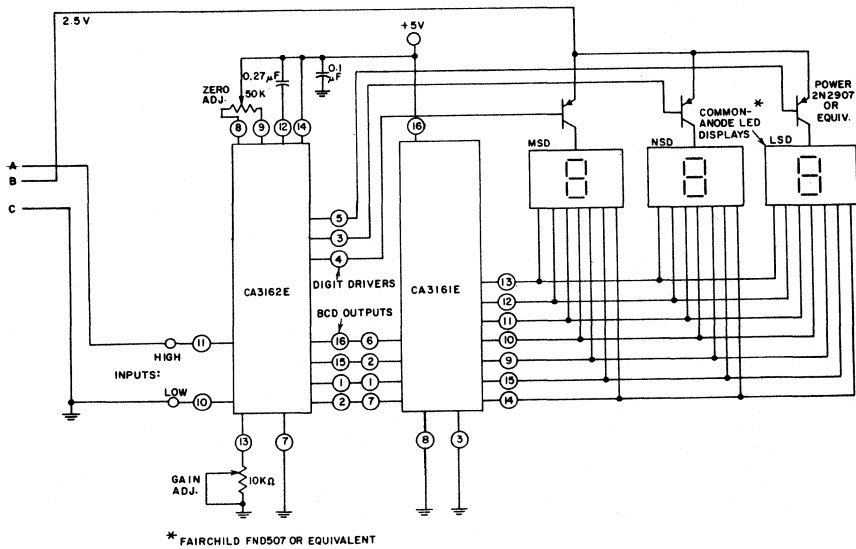
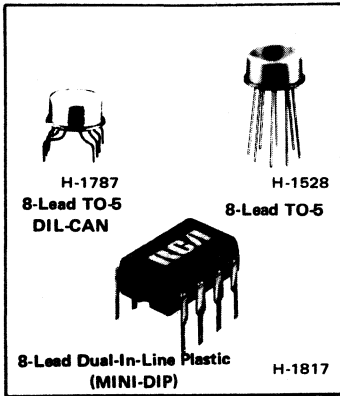


Fig. 27-Schematic diagram of digital readout scale.

CA3085, CA3085A, CA3085B Types

Positive Voltage Regulators

For Regulated Voltages from 1.7V to 46V
at Currents up to 100mA



Features

- Up to 100 mA output current
- Input and output short-circuit protection
- Load and line regulation: 0.025%
- Pin compatible with LM100 Series
- Adjustable output voltage

Applications

- Shunt voltage regulator
- Current regulator
- Switching voltage regulator
- High-current voltage regulator
- Combination positive and negative voltage regulator
- Dual tracking regulator

RCA-CA3085, CA3085A, and CA3085B are silicon monolithic integrated circuits designed specifically for service as voltage regulators at output voltages ranging from 1.7 to 46 volts at currents up to 100 milliamperes.

A block diagram of the CA3085 Series is shown in Fig. 1. The diagram shows the connecting terminals that provide access to the regulator circuit components. The voltage regulators provide important features such as: frequency compensation, short-circuit protection, temperature-compensated reference voltage, current limiting, and booster input. These devices are useful in a wide range of applications for regulating high-current, switching, shunt, and positive and negative voltages. They are also applicable for current and dual-tracking regulation.

The CA3085A and CA3085B have output current capabilities up to 100 mA and the CA3085 up to 12 mA without the use of external pass transistors. However, all the devices can provide voltage regulation at load currents greater than 100 mA with the use of suitable external pass transistors. The CA3085 Series has an unregulated input voltage ranging from 7.5 to 30 V (CA3085), 7.5 to 40 V (CA3085A), and 7.5 to 50 V (CA3085B) and a minimum regulated output voltage of 26 V (CA3085), 36 V (CA3085A), and 46 V (CA3085B).

The CA3085A is unilaterally interchangeable with the CA3055.

These types are supplied in the 8-lead TO-5 style package (CA3085, CA3085A, CA3085B, and the 8-lead TO-5 with dual-in-line formed leads ("DIL-CAN", CA3085S, CA3085AS, CA3085BS). The CA3085 is also supplied in the 8-lead dual-in-line plastic package ("MINI-DIP", CA3085E), and in chip form (CA3085H).

Type	V _{IN} Range V	V _{OUT} Range V	Max. I _{OUT} mA	Max. Load Regulation % V _{OUT}
CA3085	7.5 to 30	1.8 to 26	12*	0.1
CA3085A	7.5 to 40	1.7 to 36	100	0.15
CA3085B	7.5 to 50	1.7 to 46	100	0.15

* This value may be extended to 100 mA; however, regulation is not specified beyond 12 mA.

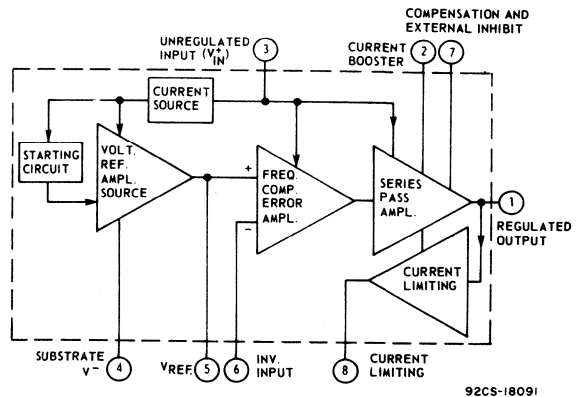


Fig. 1—Block diagram of CA3085 Series.

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CA3085, CA3085A, CA3085B Types

MAXIMUM RATINGS, ABSOLUTE-MAXIMUM VALUES at $T_A = 25^\circ\text{C}$

POWER DISSIPATION: WITHOUT HEAT SINK		WITH HEAT SINK (TO-5 ONLY)
up to $T_A = 55^\circ\text{C}$	630 mW	up to $T_C = 55^\circ\text{C}$ 1.6 W
above $T_A = 55^\circ\text{C}$ derate linearly @ $6.67 \text{ mW}/^\circ\text{C}$		above $T_C = 55^\circ\text{C}$ derate linearly at $16.7 \text{ mW}/^\circ\text{C}$

TEMPERATURE RANGE:

Operating	-55 to $+125^\circ\text{C}$
Storage	-65 to $+150^\circ\text{C}$

UNREGULATED INPUT VOLTAGE:

CA3085	30 V
CA3085A	40 V
CA3085B	50 V

LEAD TEMPERATURE (DURING SOLDERING):

At distance $1/16 \pm 1/32$ inch ($1.59 \pm 0.79\text{mm}$)
from case for 10 seconds max. $+265^\circ\text{C}$

Maximum Voltage Ratings

The following chart gives the range of voltages which can be applied to the terminals listed vertically with respect to the terminals listed horizontally. For example, the voltage range between vertical Terminal No. 7 and horizontal Terminal No. 1 is $+3$ to -10 volts.

MAXIMUM VOLTAGE RATINGS

TERMINAL No.	5	6	7	8	1	2	3	4	
5	-	+5 -5	*	*	*	*	*	+10 0	* Voltages are not normally applied between these terminals; however, voltages appearing between these terminals are safe, if the specified voltage limits between all other terminals are not exceeded. ‡ 30 V for CA3085 40 V for CA3085A 50 V for CA3085B
6	-	-	*	*	*	*	*	*	
7	-	-	-	+3 -10	+3 -10	*	*	‡ 0	
8	-	-	-	-	+5 -1	*	*	*	
1	-	-	-	-	-	+10 -‡	0 -‡	‡ 0	
2	-	-	-	-	-	-	0 -	‡ 0	
3	-	-	-	-	-	-	-	‡ 0	
4	-	-	-	-	-	-	-	Substrate & Case	

MAXIMUM CURRENT RATINGS

TERMINAL No.	I_{IN} mA	I_{OUT} mA
5	10	1.0
6	1.0	-0.1
7	1.0	-1.0
8	0.1	10
1	20	150
2	150	60
3	150	60
4	-	-

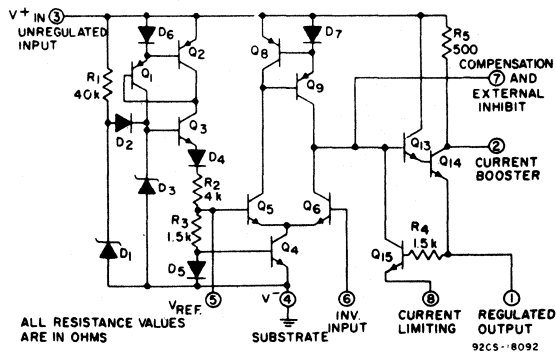


Fig.2—Schematic diagram of CA3085 Series.

CA3085, CA3085A, CA3085B Types

ELECTRICAL CHARACTERISTICS

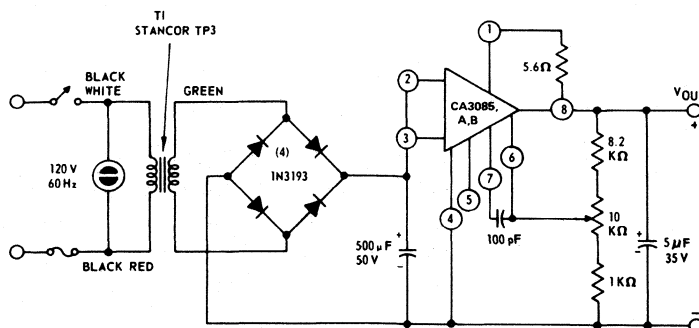
CHARACTERISTICS	SYMBOL	Test Circuit Fig. No.	TEST CONDITIONS			LIMITS						UNITS			
			T _A = 25°C [Unless indicated otherwise]			CA3085			CA3085A				CA3085B		
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.				
Reference Voltage	V _{REF}	4	V ⁺ _{IN} = 15V			1.4	1.6	1.8	1.5	1.6	1.7	1.5	1.6	1.7	V
Quiescent Regulator Current	I _{quiescent}	4	V ⁺ _{IN} = 30V			-	3.3	4.5	-	-	-	-	-	-	mA
			V ⁺ _{IN} = 40V			-	-	-	-	3.65	5	-	-	-	
			V ⁺ _{IN} = 50V			-	-	-	-	-	-	-	4.05	7	
Input Voltage Range	V _{IN} (range)	-	-			7.5	-	30	7.5	-	40	7.5	-	50	V
Maximum Output Voltage	V _O (max.)	4	V ⁺ _{IN} = 30, 40, 50V#; R _L = 365Ω; Term. No. 6 to Gnd.			26	27	-	36	37	-	46	47	-	V
Minimum Output Voltage	V _O (min.)	4	V ⁺ _{IN} = 30V			-	1.6	1.8	-	1.6	1.7	-	1.6	1.7	V
Input-Output Voltage Differential	V _{IN} -V _{OUT}	-	-			4	-	28	4	-	38	3.5	-	48	V
Limiting Current	I _{LIM}	7	V ⁺ _{IN} = 16V, V ⁺ _{OUT} = 10V R _{SCP} * = 6Ω			-	96	120	-	96	120	-	96	120	mA
Load Regulation [●]	-	-	I _L = 1 to 100mA, R _{SCP} = 0			-	-	-	-	0.025	0.15	-	0.025	0.15	%V _{OUT}
			I _L = 1 to 100mA, R _{SCP} = 0 T _A = 0°C to +70°C			-	-	-	-	0.035	0.6	-	0.035	0.6	
			I _L = 1 to 12mA, R _{SCP} = 0			-	0.003	0.1	-	-	-	-	-	-	
Line Regulation [▲]	-	-	I _L = 1 mA, R _{SCP} = 0			-	0.025	0.1	-	0.025	0.075	-	0.025	0.04	%V
			I _L = 1 mA, R _{SCP} = 0 T _A = 0°C to +70°C			-	0.04	0.15	-	0.04	0.1	-	0.04	0.08	
Equivalent Noise Output Voltage	V _{NOISE}	11	V ⁺ _{IN} = 25V		C _{REF} = 0		-	0.5	-	0.5	-	0.5	-	mV p-p	
				C _{REF} = 0.22μF		-	0.3	-	0.3	-	0.3	-			
Ripple Rejection	-	12	V ⁺ _{IN} = 25V		C _{REF} = 0		-	50	-	50	-	45	50	dB	
			f = 1kHz		C _{REF} = 2μF		-	56	-	56	-	50	56		
Output Resistance	r _o	12	V ⁺ _{IN} = 25V, f = 1kHz			-	0.075	1.1	-	0.075	0.3	-	0.075	0.3	Ω
Temperature Coefficient of Reference and Output Voltages	ΔV _{REF} , ΔV _O	-	I _L = 0, V _{REF} = 1.6V			-	0.0035	-	-	0.0035	-	-	0.0035	-	%/°C
Load Transient Recovery Time:	Turn On	t _{ON}	16	V ⁺ _{IN} = 25V, +50mA Step			-	1	-	-	1	-	1	-	μs
				Turn Off			t _{OFF}	-	3	-	-	3	-	3	
Line Transient Recovery Time:	Turn On	t _{ON}	-	V ⁺ _{IN} = 25V, f = 1kHz, 2V Step			-	0.8	-	-	0.8	-	0.8	-	μs
				Turn Off			t _{OFF}	-	0.4	-	-	0.4	-	0.4	

30V (CA3085), 40V (CA3085A), 50V (CA3085B)

* RSCP: Short-circuit protection resistance

● Load Regulation = $\frac{\Delta V_{OUT}}{V_{OUT}(initial)} \times 100\%$

▲ Line Regulation = $\frac{(\Delta V_{OUT})}{[V_{OUT}(initial)] (\Delta V_{IN})} \times 100\%$



V_{OUT} = 3.5V to 20V (0 TO 90mA)
REGULATION = 0.2% (LINE AND LOAD)
RIPPLE < 0.5mV AT FULL LOAD

92CS-18093

Fig. 3—Application of the CA3085 Series in a typical power supply.

Linear Integrated Circuits

CA3085, CA3085A, CA3085B Types

TEST CIRCUITS AND TYPICAL CHARACTERISTICS CURVES FOR CA3085 SERIES

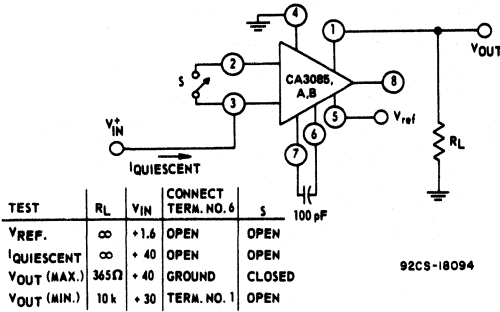


Fig. 4—Test circuit for V_{REF} , $I_{quiescent}$, $V_{OUT(max.)}$, $V_{OUT(min.)}$.

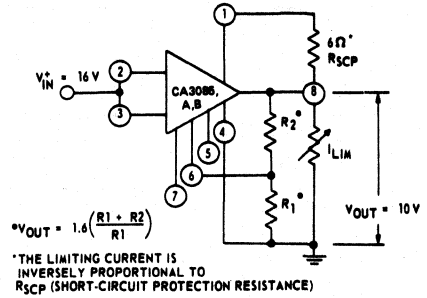


Fig. 7—Test circuit for limiting current

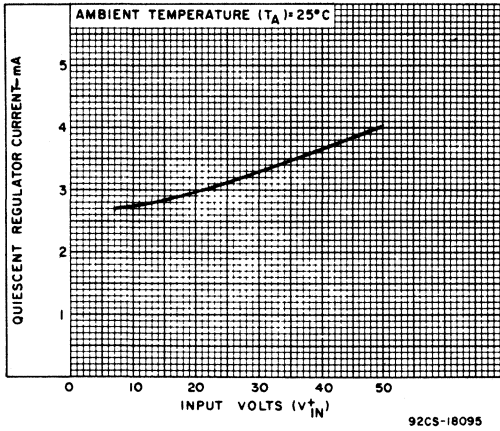


Fig. 5— $I_{quiescent}$ vs. V_{IN}^+ .

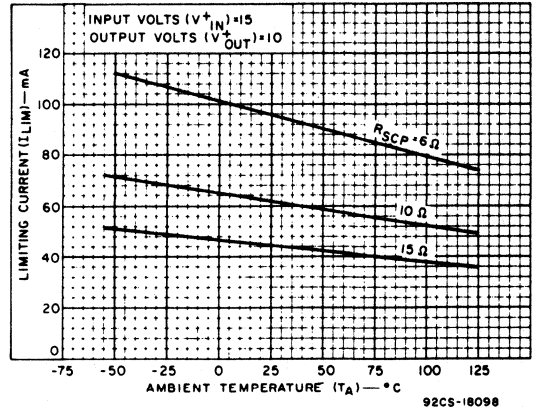


Fig. 8— I_{LIM} vs. T_A .

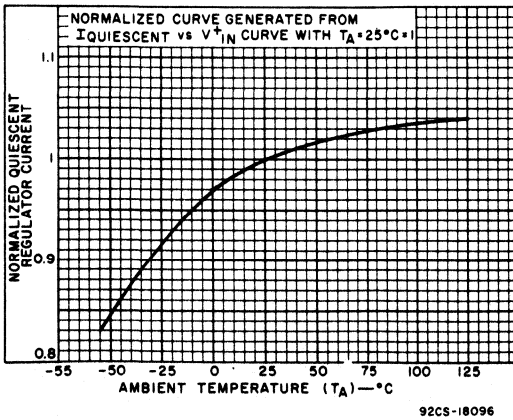


Fig. 6—Normalized $I_{quiescent}$ vs. T_A .

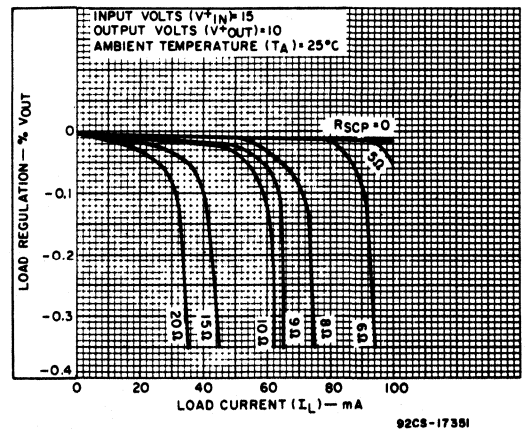


Fig. 9—Load regulation characteristics.

CA3085, CA3085A, CA3085B Types

TEST CIRCUITS AND TYPICAL CHARACTERISTICS CURVES FOR CA3085 SERIES

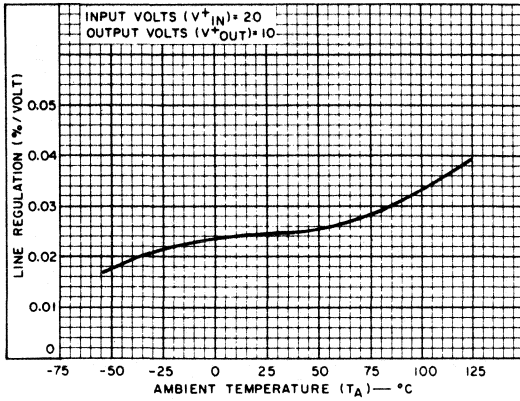


Fig. 10—Line regulation temperature characteristics.

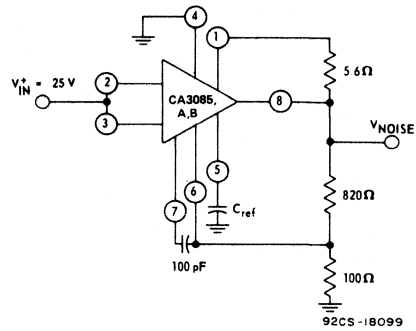


Fig. 11—Test circuit for noise voltage.

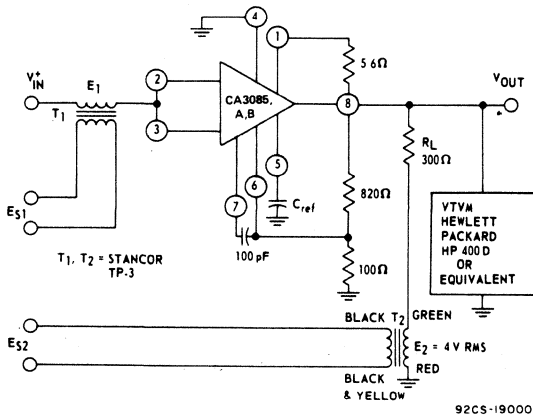


Fig. 12—Test circuit for ripple rejection and output resistance.

TEST PROCEDURES FOR TEST CIRCUIT FOR RIPPLE REJECTION AND OUTPUT RESISTANCE

Output Resistance

Conditions:

1. $V_{IN} = +25V$, $C_{REF} = 0$, Short E_1
2. Set E_2 at 1 kHz so that $E_2 = 4V$ rms
3. Read V_{OUT} on a VTVM, such as a Hewlett-Packard, HP400D or equivalent
4. Calculate R_{OUT} from $R_{OUT} = V_{OUT} (|R_L/E_2)$

Ripple Rejection - I

Conditions:

1. $V_{IN} = +25V$, $C_{REF} = 0$, Short E_2
2. Set E_1 at 1 kHz so that $E_1 = 3V$ rms
3. Read V_{OUT} on a VTVM, such as a Hewlett-Packard, HP400D or equivalent
4. Calculate Ripple Rejection from $20 \log (E_1/V_{OUT})$

Ripple Rejection - II

Conditions:

1. Repeat Ripple Rejection I with $C_{REF} = 2 \mu F$

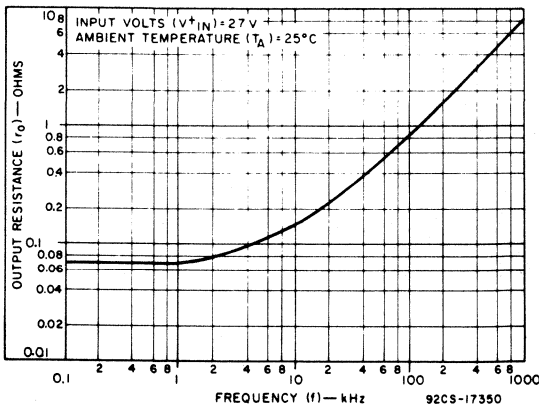


Fig. 13— r_o vs. f .

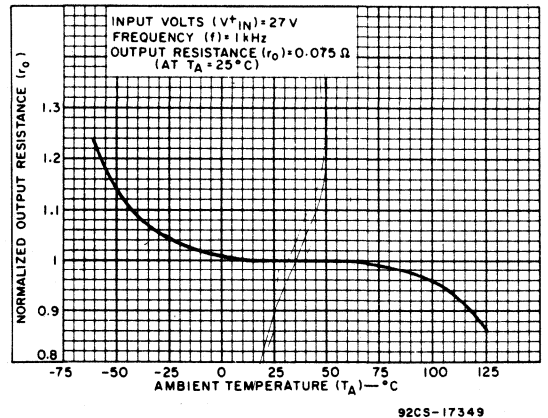


Fig. 14—Normalized r_o vs. T_A .

Linear Integrated Circuits

CA3085, CA3085A, CA3085B Types

TEST CIRCUIT AND TYPICAL CHARACTERISTICS CURVES FOR CA3085 SERIES

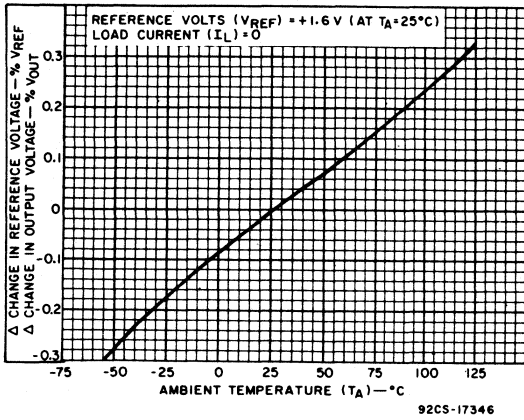


Fig.15—Temperature coefficient of V_{REF} and V_{OUT} .

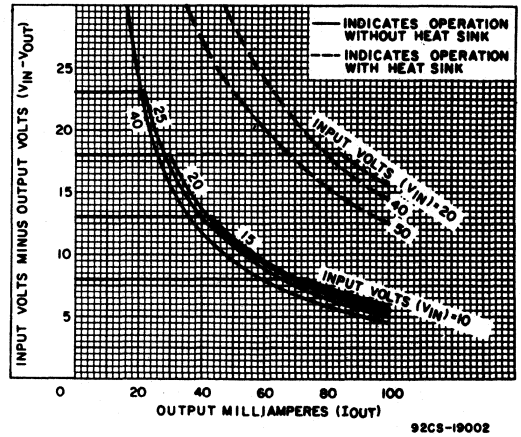


Fig.17—Dissipation limitation ($V_{IN} - V_{OUT}$ vs. I_{OUT}).

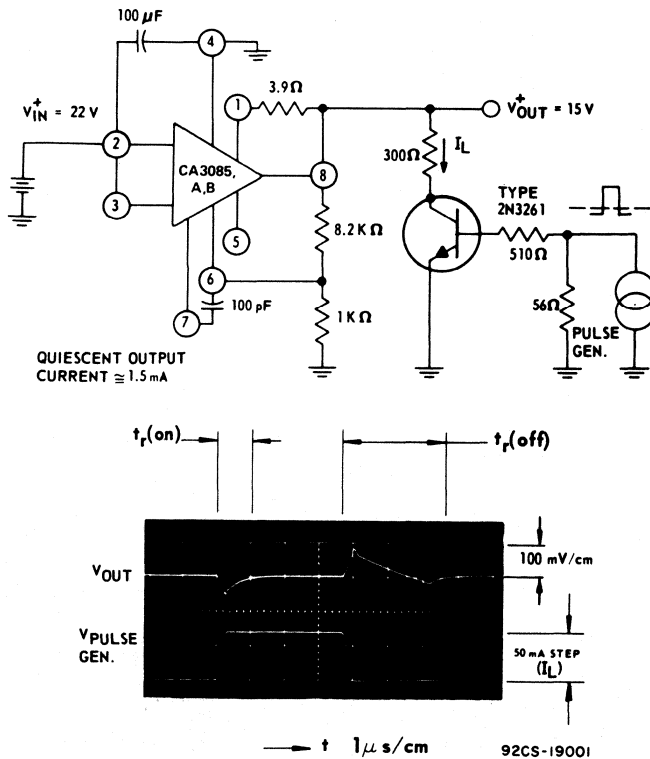


Fig.16—Turn-on and turn-off recovery time test circuit with associated waveforms.

CA3085, CA3085A, CA3085B Types

TYPICAL REGULATOR CIRCUITS USING THE CA3085 SERIES

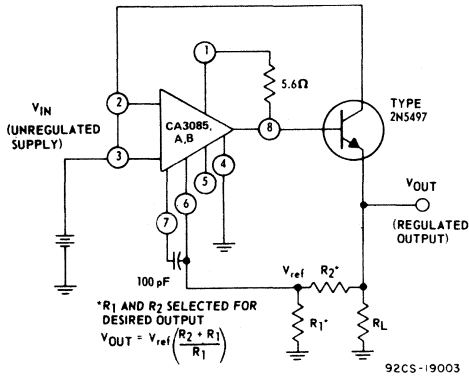


Fig. 18—Typical high-current voltage regulator circuit.

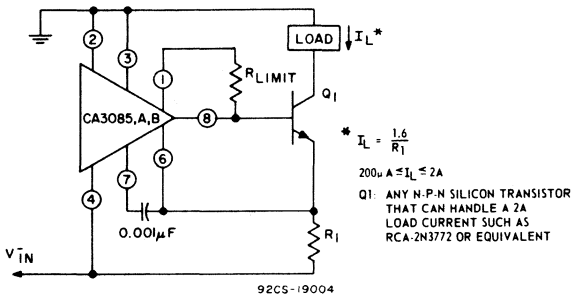
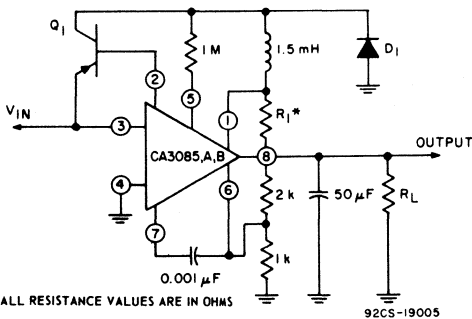
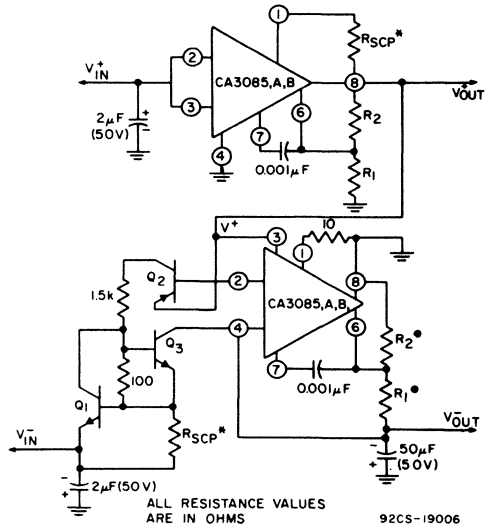


Fig. 19—Typical current regulator circuit.



D1: RCA-1N1763A OR EQUIVALENT
 Q1: RCA-2N5322 OR EQUIVALENT
 *R₁ = 0.7 I_L (MAX.)

Fig. 20—Typical switching regulator circuit.



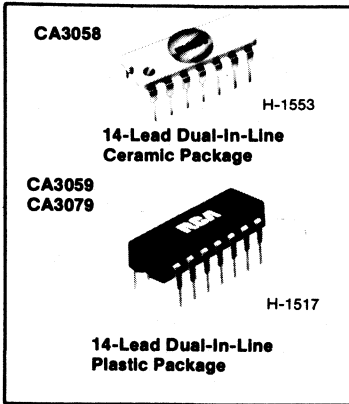
ALL RESISTANCE VALUES ARE IN OHMS
 Q1: RCA-2N2102 OR EQUIVALENT
 Q2: ANY P-N-P SILICON TRANSISTOR (RCA-2N5322 OR EQUIVALENT)
 Q3: ANY N-P-N SILICON TRANSISTOR THAT CAN HANDLE THE DESIRED LOAD CURRENT (RCA-2N3772 OR EQUIVALENT)

* $V_{OUT} = \left(\frac{R_1 + R_2}{R_1} \right)$
 *R_{SCP}: SHORT-CIRCUIT PROTECTION RESISTANCE

Fig. 21—Combination positive and negative voltage regulator circuit.

Linear Integrated Circuits

CA3058, CA3059, CA3079



Zero-Voltage Switches

For 50/60 and 400 Hz Thyristor Control Applications

Applications:

- Relay control
- Valve control
- Synchronous switching of flashing lights
- On-off motor switching
- Differential comparator with self-contained power supply for industrial applications
- Photosensitive control
- Power one-shot control
- Heater control
- Lamp control

The RCA-CA3058, CA3059, and CA3079 zero-voltage switches are monolithic silicon integrated circuits designed to control a thyristor in a variety of AC power switching applications for AC input voltages of 24 V, 120 V, 208/230 V, and 277 V at 50/60 and 400 Hz. Each of the zero-voltage switches incorporates 4 functional blocks (see Fig. 1) as follows:

1. Limiter-Power Supply — Permits operation directly from an AC line.
2. Differential On/Off Sensing Amplifier — Tests the condition of external sensors or command signals. Hysteresis or proportional-control capability may easily be implemented in this section.
3. Zero-Crossing Detector — Synchronizes the output pulses of the circuit at the time when the AC cycle is at zero voltage point; thereby eliminating radio-frequency interference (RFI) when used with resistive loads.
4. Triac Gating Circuit — Provides high-current pulses to the gate of the power controlling thyristor.

In addition, the CA3058 and CA3059 provide the following

important auxiliary functions (see Fig. 1):

1. A built-in protection circuit that may be actuated to remove drive from the triac if the sensor opens or shorts.
2. Thyristor firing may be inhibited through the action of an internal diode gate connected to Terminal 1.
3. High-power dc comparator operation is provided by overriding the action of the zero-crossing detector. This is accomplished by connecting Terminal 12 to Terminal 7. Gate current to the thyristor is continuous when Terminal 13 is positive with respect to Terminal 9.

For an explanation of these functions see Operating Considerations, page 11. For detailed application information, see companion Application Note, ICAN-6182, "Features and Applications of RCA Integrated-Circuit Zero-Voltage Switches (CA3058, CA3059, and CA3079)".

The CA3058 is supplied in a hermetic 14-lead dual-in-line ceramic package. Types CA3059 and CA3079 are supplied in 14-lead dual-in-line plastic packages. The CA3079 is also available in chip form (H suffix).

Features

	CA3058	CA3059	CA3079
■ 24V, 120V, 208/230V, 277V at 50 60, or 400 Hz operation	✓	✓	✓
■ Differential Input	✓	✓	✓
■ Low Balance Input Current (max.) - μ A	1	1	2
■ Built-in Protection Circuit for opened or shorted sensor (Term. 14)	✓	✓	
■ Sensor Range (Rx) - k Ω	2 to 100	2 to 100	2 to 50
■ DC Mode (Term 12)	✓	✓	
■ External Trigger (Term 6)	✓	✓	
■ External Inhibit (Term 1)	✓	✓	
■ DC Supply Volts (max.)	14	14	10
■ Operating Temperature Range - $^{\circ}$ C		-55 to +125	

Power Control Circuits

CA3058, CA3059, CA3079

MAXIMUM RATINGS

Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

DC SUPPLY VOLTAGE (BETWEEN TERMS. 2 AND 7):	
CA3058, CA3059	14 V
CA3079	10 V
DC SUPPLY VOLTAGE (BETWEEN TERMS. 2 AND 8):	
CA3058, CA3059	14 V
CA3079	10 V
PEAK SUPPLY CURRENT (TERMS. 5 AND 7)	± 50 mA
OUTPUT PULSE CURRENT (TERM. 4)	150 mA

POWER DISSIPATION:

Up to $T_A = 75^\circ\text{C}$ - CA3058	700 mW
Up to $T_A = 55^\circ\text{C}$ - CA3059, CA3079	700 mW
Above $T_A = 75^\circ\text{C}$ - CA3058	Derate Linearly 8 mW/ $^\circ\text{C}$
Above $T_A = 55^\circ\text{C}$ - CA3059, CA3079	Derate linearly 6.67 mW/ $^\circ\text{C}$

AMBIENT TEMPERATURE RANGE:

Operating	-55 to +125 $^\circ\text{C}$
Storage	-65 to +150 $^\circ\text{C}$

LEAD TEMPERATURE (DURING SOLDERING):

At a distance 1/16" \pm 1/32" (1.59 \pm 0.79 mm) from case for 10 seconds max.	+265 $^\circ\text{C}$
--	-----------------------

MAXIMUM VOLTAGE RATINGS at $T_A = 25^\circ\text{C}$ **MAXIMUM CURRENT RATINGS**

TERMINAL NO.	MAXIMUM VOLTAGE RATINGS (V)														I _{IN} mA	I _{OUT} mA
	1	2	3	4	5	6	7	8	9	10	11	12	13	14		
1 Note 3	*	*	*	*	15	10	*	*	*	*	*	*	*	*	10	0.1
2		0	0	2	0	0	0	0	0	0	0	*	0	0	150	10
3		-15	-15	-14	-14	-14	-14	-14	-14	-14	-14	*	-14	-14	*	*
4			0	*	*	*	*	*	*	*	*	*	*	*	0.1	150
5 Note 1					*	2	*	*	*	*	*	*	*	*	50	10
6 Note 3						7	*	*	*	*	*	*	*	*	*	*
7						-10	*	*	*	*	*	*	*	*	*	*
8										14	*	*	*	*	0.1	2
9										10	*	*	*	*	*	*
10										0	*	*	*	*	*	*
11															*	*
12 Note 3															50	50
13															*	*
14 Note 3															2	2

This chart gives the range of voltages which can be applied to the terminals listed horizontally with respect to the terminals listed vertically. For example, the voltage range of horizontal Terminal 6 to vertical Terminal 4 is 2 to -10 volts.

Note 1 - Resistance should be inserted between Terminal 5 and external supply or line voltage for limiting current into Terminal 5 to less than 50 mA.

Note 2 - Resistance should be inserted between Terminal 14 and external supply for limiting current into Terminal 14 to less than 2 mA.

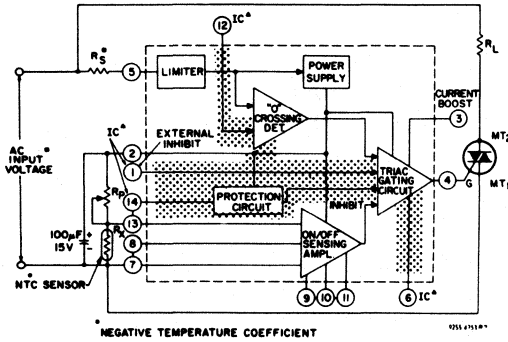
Note 3 - For the CA3079 indicated terminal is internally connected and, therefore, should not be used.

▲ For CA3079 (0 to -10 V).

* Voltages are not normally applied between these terminals; however, voltages appearing between these terminals are safe, if the specified voltage limits between all other terminals are not exceeded.

Linear Integrated Circuits

CA3058, CA3059, CA3079



AC Input Voltage (50/60 or 400 Hz) V AC	Input Series Resistor (RS) k Ω	Dissipation Rating for RS W
24	2	0.5
120	10	2
208/230	20	4
277	25	5

NOTE:

Circuitry, within shaded areas, not included in CA3079

■ See chart

▲ IC = Internal Connection -- DO NOT USE
(Terminal Restriction applies only to CA3079).

Fig. 1—Functional block diagram of CA3058, CA3059, and CA3079.

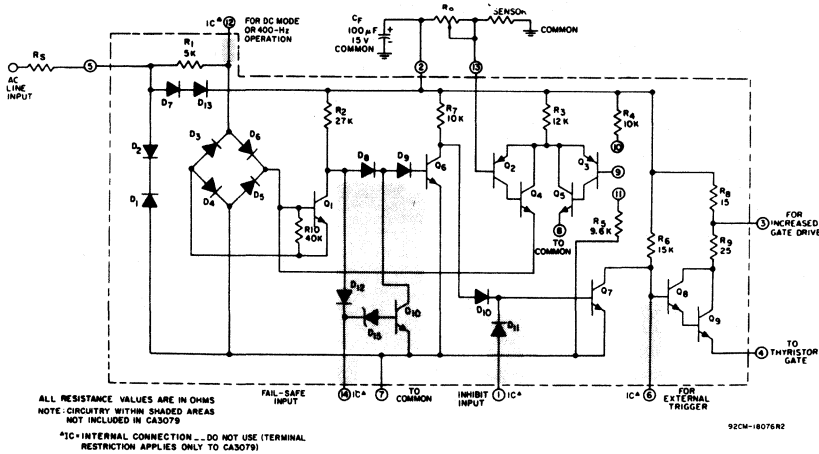


Fig. 2—Schematic diagram of CA3058, CA3059, and CA3079.

ELECTRICAL CHARACTERISTICS (For all types, unless indicated otherwise)

All voltages are measured with respect to Terminal 7.

CHARACTERISTIC	TEST CONDITIONS T _A = 25°C (Unless Indicated Otherwise)	LIMITS			UNITS
		Min.	Typ.	Max.	
For Operating at 120 V rms, 50-60 Hz (AC Line Voltage)*					
DC Supply Voltage, V _S					
Inhibit Mode					
At 50/60 Hz	R _S = 8 kΩ, I _L = 0	6.1	6.5	7	V
At 400 Hz	R _S = 10 kΩ, I _L = 0	—	6.8	—	V
At 50/60 Hz	R _S = 5 kΩ, I _L = 2 mA	—	6.4	—	V
Pulse Mode					
At 50/60 Hz	R _S = 8 kΩ, I _L = 0	6	6.4	7	V
At 400 Hz	R _S = 10 kΩ, I _L = 0	—	6.7	—	V
At 50/60 Hz	R _S = 5 kΩ, I _L = 2 mA	—	6.3	—	V
At 50/60 Hz (CA3058)	R _S = 8 kΩ, I _L = 0	5.5	—	7.5	V
See Fig. 3	T _A = -55 to +125°C				

Power Control Circuits
CA3058, CA3059, CA3079

ELECTRICAL CHARACTERISTICS (For all types, unless indicated otherwise) (Cont'd)
All voltages are measured with respect to Terminal 7.

CHARACTERISTIC	TEST CONDITIONS $T_A = 25^\circ\text{C}$ (Unless Indicated Otherwise)	LIMITS			UNITS
		Min.	Typ.	Max.	
For Operating at 120 V rms, 50-60 Hz (AC Line Voltage)*					
Gate Trigger Current, $I_{GT}^{(4)}$ <i>See Figs. 4, 5(a)</i>	Terms. 3 and 2 connected, $V_{GT} = 1\text{ V}$	—	105	—	mA
Peak Output Current (Pulsed), $I_{OM}^{(4)}$ With Internal Power Supply	Term. 3 open, Gate Trigger Voltage (V_{GT}) = 0	50	84	—	mA
	Terms. 3 and 2 connected, Gate Trigger Voltage (V_{GT}) = 0	90	124	—	mA
	Term. 3 open, $V^+ = 12\text{ V}$, $V_{GT} = 0$	—	170	—	mA
With External Power Supply <i>See Figs. 5, 6</i>	Terms. 3 and 2 connected, $V^+ = 12\text{ V}$, $V_{GT} = 0$	—	240	—	mA
Inhibit Input Ratio, V_g/V_2 All Types	Voltage Ratio of Term. 9 to 2	0.465	0.485	0.520	—
CA3058 <i>See Fig. 7</i>	$T_A = -55\text{ to }+125^\circ\text{C}$	0.450	—	0.520	—
Total Gate Pulse Duration:*					
For positive dv/dt, t_p 50-60 Hz	$C_{EXT} = 0$	70	100	140	μs
400 Hz	$C_{EXT} = 0$, $R_{EXT} = \infty$	—	12	—	μs
For negative dv/dt, t_N 50-60 Hz	$C_{EXT} = 0$	70	100	140	μs
400 Hz <i>See Fig. 8</i>	$C_{EXT} = 0$, $R_{EXT} = \infty$	—	10	—	μs
Pulse Duration After Zero Crossing (50-60 Hz): For positive dv/dt, t_{p1} For negative dv/dt, t_{N1} <i>See Fig. 8</i>	$C_{EXT} = 0$ $R_{EXT} = \infty$	—	50 60	—	μs μs
Output Leakage Current, I_4 Inhibit Mode: All Types		—	0.001	10	μA
CA3058 <i>See Fig. 9</i>	$T_A = -55\text{ to }+125^\circ\text{C}$	—	—	20	μA
Input Bias Current, I_1 CA3058, CA3059 CA3079 <i>See Fig. 10</i>		—	220	1000	nA
Common-Mode Input Voltage Range, V_{CMR}	Terms. 9 and 13 connected	—	1.5 to 5	—	V
Sensitivity, ΔV_{13}^\neq (Pulse Mode) <i>See Figs. 5(a), 12</i>	Term. 12 open	—	6	—	mV

\neq Required voltage change at Term. 13 to either turn OFF the triac when ON or turn ON the triac when OFF.

* Pulse duration in 50 Hz applications is approximately 15% longer than shown in Fig. 8(b).

• The values given in the Electrical Characteristics Chart at 120 V also apply for operation at input voltages of 24 V, 208/230 V, and 277 V, except for Pulse Duration. However, the series resistor (R_G) must have the indicated value, shown in the chart in Fig. 1, for the specified input voltage.

Linear Integrated Circuits

CA3058, CA3059, CA3079

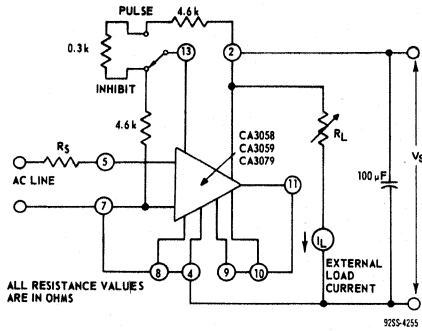


Fig. 3(a)—DC supply voltage test circuit for CA3058, CA3059, and CA3079.

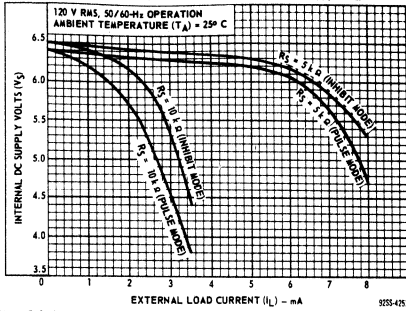


Fig. 3(c)—DC supply voltage vs. external load current for CA3058, CA3059, and CA3079.

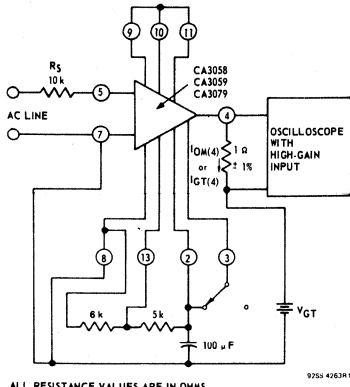


Fig. 5(a)—Peak output (pulsed) and gate trigger current with internal power supply test circuit for CA3058, CA3059, and CA3079.

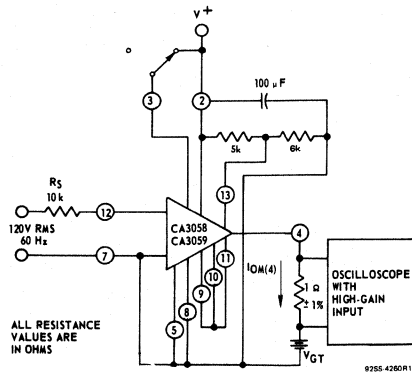


Fig. 6(a)—Peak output current (pulsed) with external power supply test circuit for CA3058 and CA3059.

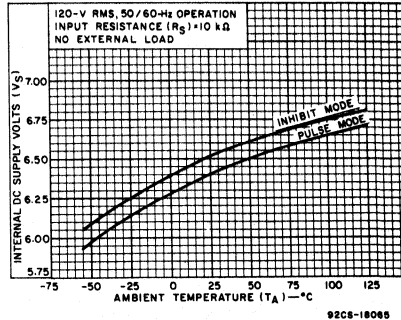


Fig. 3(b)—DC supply voltage vs. ambient temperature for CA3058, CA3059, and CA3079.

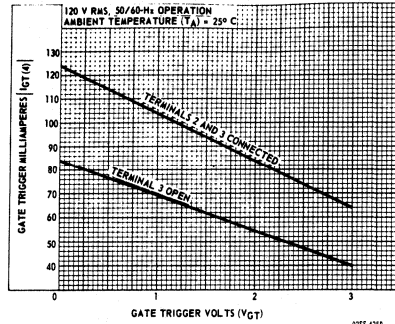


Fig. 4—Gate trigger current vs. gate trigger voltage for CA3058, CA3059, and CA3079.

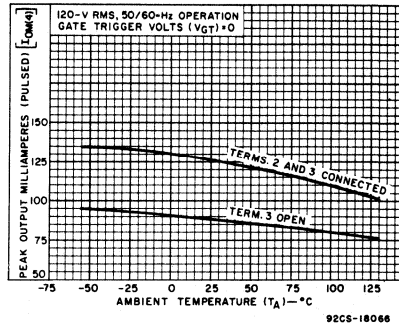


Fig. 5(b)—Peak output current (pulsed) vs. ambient temperature for CA3058, CA3059, and CA3079.

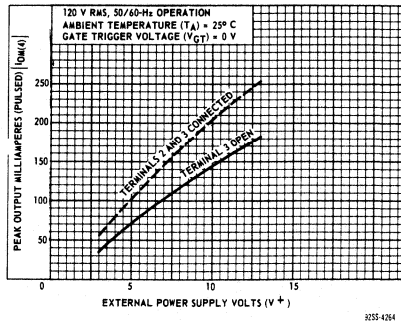


Fig. 6(b)—Peak output current (pulsed) vs. external power supply voltage for CA3058 and CA3059.

Power Control Circuits

CA3058, CA3059, CA3079

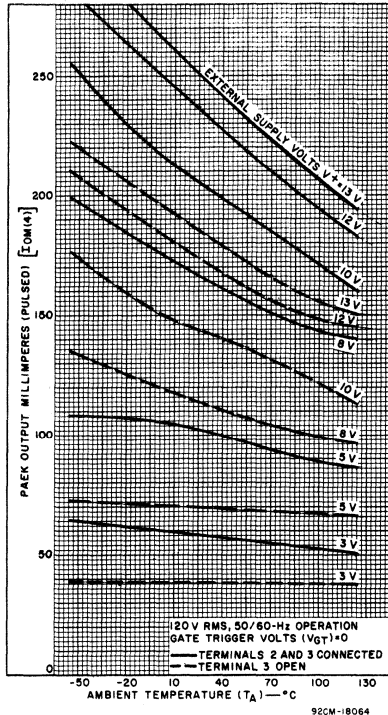
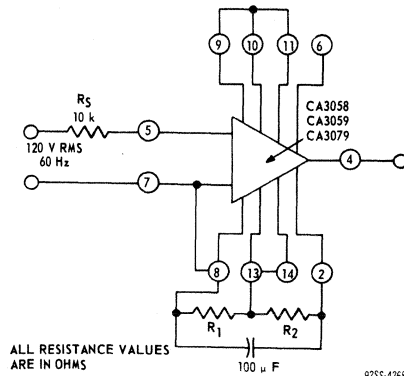


Fig. 6(c)—Peak output current (pulsed) vs. ambient temperature for CA3058 and CA3059.



ALL RESISTANCE VALUES ARE IN OHMS

925S-4268

Fig. 7(a)—Input inhibit voltage ratio test circuit for CA3058, CA3059, and CA3079.

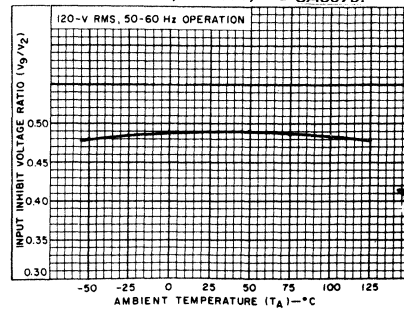
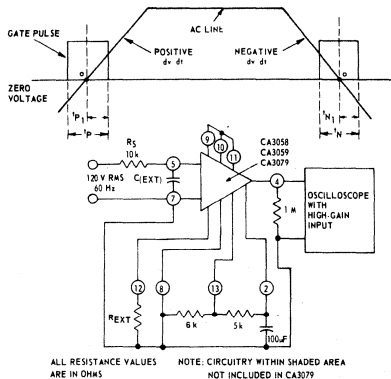


Fig. 7(b)—Input inhibit voltage ratio vs. ambient temperature for CA3058, CA3059, and CA3079.



ALL RESISTANCE VALUES ARE IN OHMS

NOTE: CIRCUITRY WITHIN SHADED AREA NOT INCLUDED IN CA3079

92CS-18064

Fig. 8(a)—Gate pulse duration test circuit with associated waveform for CA3058, CA3059, and CA3079.

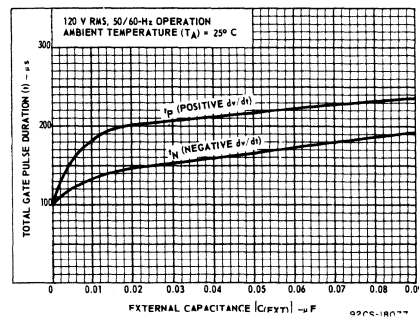


Fig. 8(b)—Total gate pulse duration vs. external capacitance for CA3058, CA3059, and CA3079.

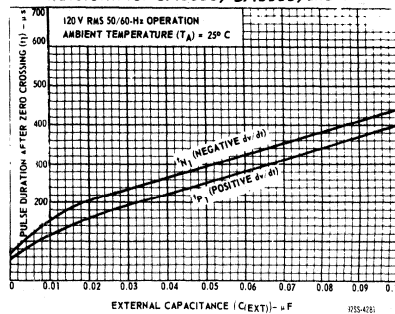


Fig. 8(c)—Pulse duration after zero crossing vs. external capacitance for CA3058, CA3059, and CA3079.

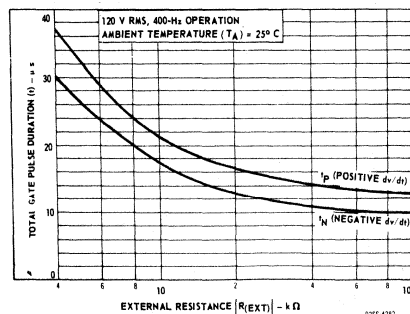


Fig. 8(d)—Total gate pulse duration vs. external resistance for CA3058 and CA3059.

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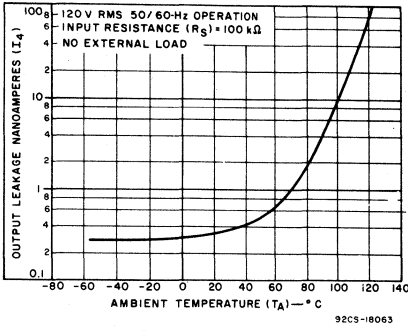


Fig. 9—Output leakage current (inhibit mode) vs. ambient temperature for CA3058, CA3059, and CA3079.

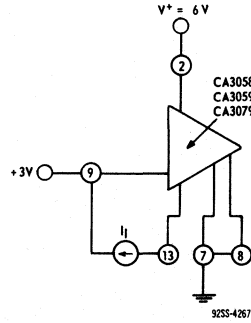
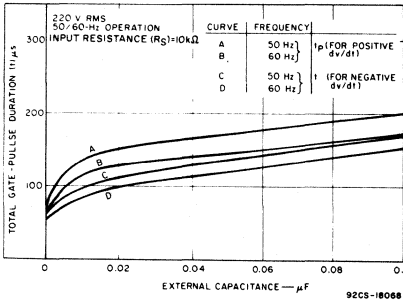
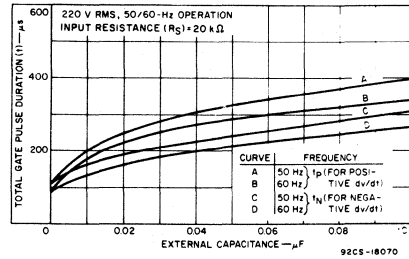


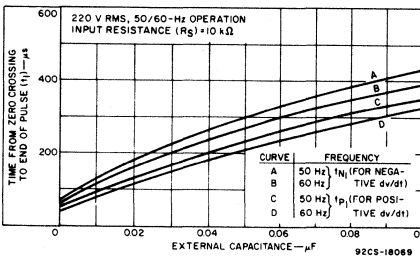
Fig. 10—Input bias current test circuit for CA3058, CA3059, and CA3079.



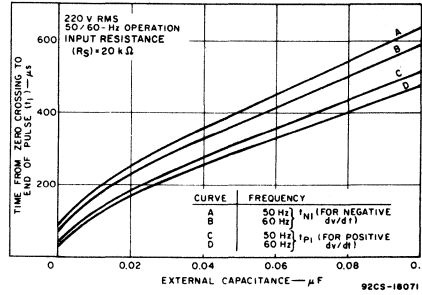
(a)



(b)



(c)



(d)

Fig. 11—Relative pulse width and location of zero crossing for 220-volt operation for CA3058, CA3059, and CA3079.

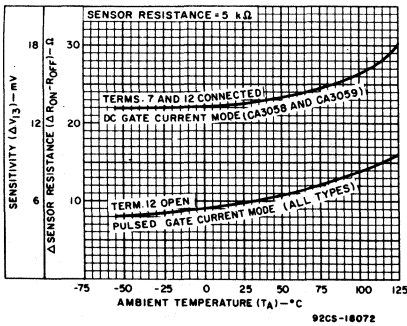


Fig. 12—Sensitivity vs. ambient temperature for CA3058, CA3059, and CA3079.

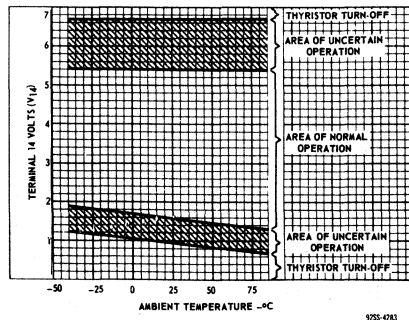


Fig. 13—Operating regions for built-in protection circuit for CA3058 and CA3059.

Power Control Circuits

CA3058, CA3059, CA3079

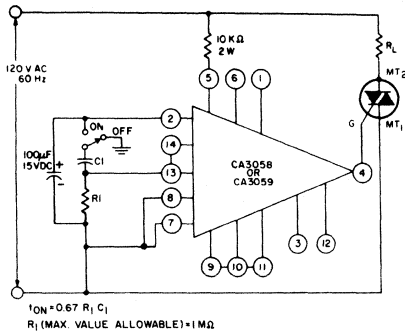


Fig. 14—Line-operated one-shot timer.

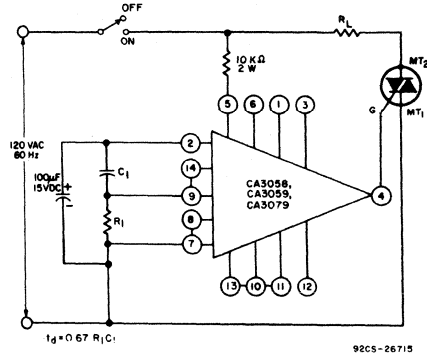


Fig. 15—Line-operated thyristor control time delay turn-on circuit.

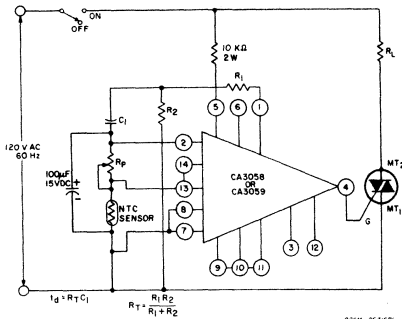


Fig. 16—On/off temperature control circuit with delayed turn-on.

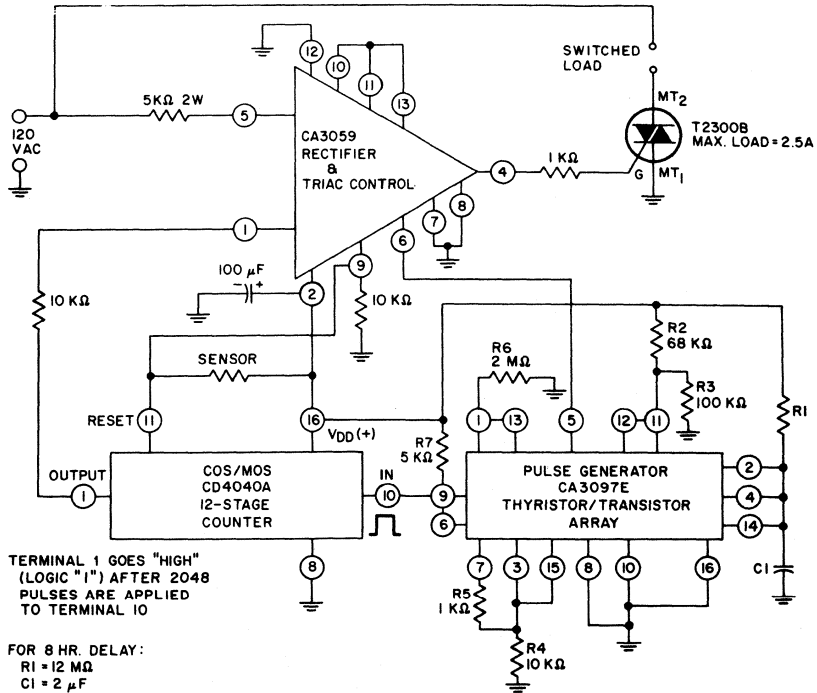


Fig. 17(a)—Line-operated IC timer for long time periods.

Linear Integrated Circuits

CA3058, CA3059, CA3079

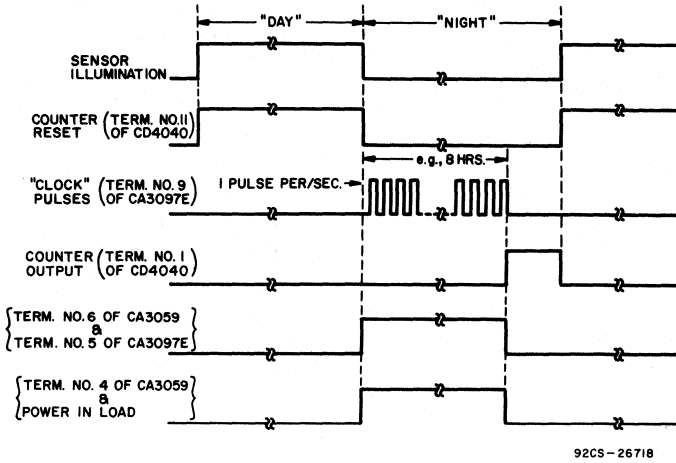


Fig. 17(b)—Timing diagram for Fig. 17(a).

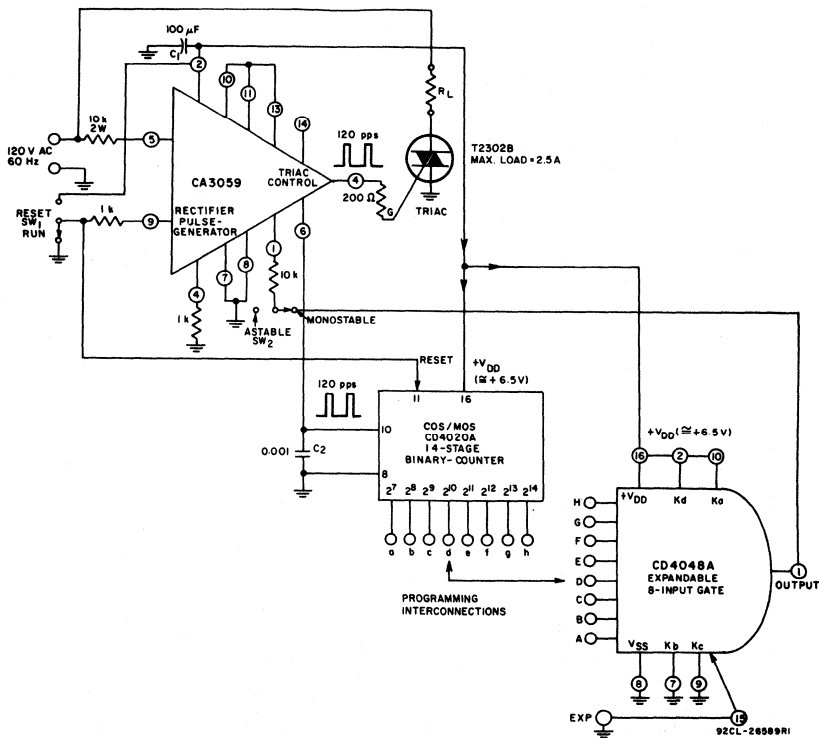


Fig. 18(a)—Programmable ultra-accurate line-operated timer.
(Programmable over the range from 0.5333 seconds to 2 minutes, 16 seconds in 0.5333-second increments)

Power Control Circuits
CA3058, CA3059, CA3079

Time Periods ($t = 0.53333\text{ s}$)	1 t	2 t	4 t	8 t	16 t	32 t	64 t	128 t	t_o
Terminals									
CD4020A	a	b	c	d	e	f	g	h	
CD4048A	A	B	C	D	E	F	G	H	
	C	NC	NC	NC	NC	NC	NC	NC	1 t
	NC	C	NC	NC	NC	NC	NC	NC	2 t
	C	C	NC	NC	NC	NC	NC	NC	3 t
	NC	NC	C	NC	NC	NC	NC	NC	4 t
	C	NC	C	NC	NC	NC	NC	NC	5 t
	NC	C	C	NC	NC	NC	NC	NC	6 t
	C	C	C	NC	NC	NC	NC	NC	7 t
	NC	NC	NC	C	NC	NC	NC	NC	8 t
	C	NC	NC	C	NC	NC	NC	NC	9 t
	NC	C	NC	C	NC	NC	NC	NC	10 t
	C	C	NC	C	NC	NC	NC	NC	11 t
	NC	NC	C	C	NC	NC	NC	NC	12 t
	C	NC	C	C	NC	NC	NC	NC	13 t
	NC	C	C	C	NC	NC	NC	NC	14 t
	C	C	C	C	NC	NC	NC	NC	15 t
	C	C	C	C	NC	C	C	NC	111 t
	NC	NC	NC	NC	C	C	C	NC	112 t
	C	NC	NC	NC	C	C	C	NC	113 t
	C	C	C	C	C	C	C	C	255 t

Notes:

t_o = Total time delay = $n_1 t + n_2 t + \dots + n_n t$.

C = Connect. For example, interconnect terminal a of the CD4020A and terminal A of the CD4048A.

NC = No Connection. For example, terminal b of the CD4020A open and terminal B of the CD4048A connected to $+V_{DD}$ bus.

Fig. 18(b) — "Programming" table for Fig. 18(a).

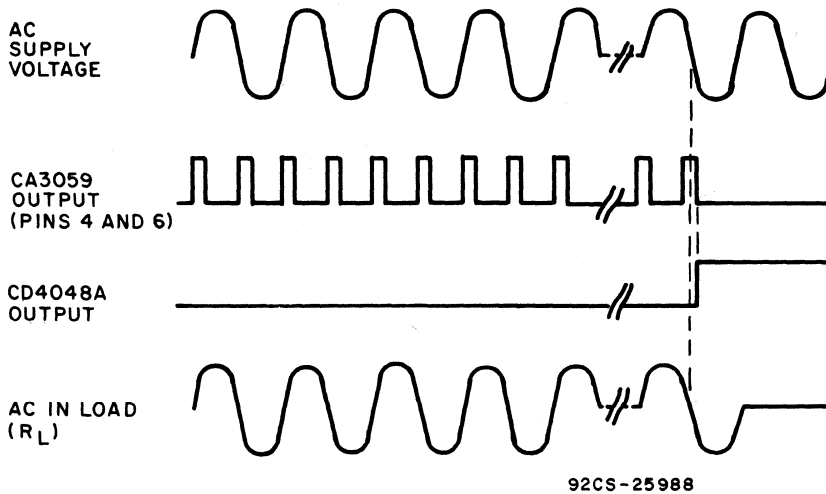


Fig. 18(c) — Timing diagram for Fig. 18(a).

CA3058, CA3059, CA3079

OPERATING CONSIDERATIONS

Power Supply Considerations for CA3058, CA3059, and CA3079

The CA3058, CA3059, and CA3079 are intended for operation as self-powered circuits with the power supplied from an AC line through a dropping resistor. The internal supply is designed to allow for some current to be drawn by the auxiliary power circuits. Typical power supply characteristics are given in Figs. 3(b) and 3(c).

Power Supply Considerations for CA3058 and CA3059

The output current available from the internal supply may not be adequate for higher power applications. In such applications an external power supply with a higher voltage should be used with a resulting increase in the output level. (See Fig. 5 for the peak output current characteristics). When an external power supply is used, Terminal 5 should be connected to Terminal 7 and the synchronizing voltage applied to Terminal 12 as illustrated in Fig. 5(a).

Operation of Built-in Protection for the CA3058, CA3059

A special feature of the CA3058 and CA3059 is the inclusion of a protection circuit which, when connected, removes power from the load if the sensor either shorts or opens. The protection circuit is activated by connecting Terminal 14 to Terminal 13 as shown in Fig. 1. To assure proper operation of the protection circuit the following conditions should be observed:

1. Use the internal supply and limit the external load current to 2 mA with a 5 k Ω dropping resistor.

2. Set the value of R_p and sensor resistance (R_x) between 2 k Ω and 100 k Ω .
3. The ratio of R_x to R_p , typically, should be greater than 0.33 and less than 3. If either of these ratios is not met with an unmodified sensor over the entire anticipated temperature range, then either a series or shunt resistor must be added to avoid undesired activation of the circuit.

If operation of the protection circuit is desired under conditions other than those specified above, then apply the data given in Fig. 13.

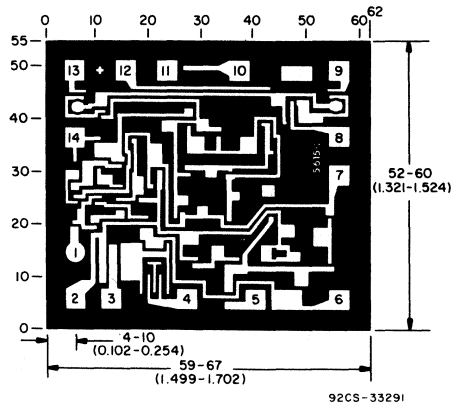
External Inhibit Function for the CA3058 and CA3059

A priority inhibit command may be applied to Terminal 1. The presence of at least +1.2 V at 10 μ A will remove drive from the thyristor. This required level is compatible with DTL or T²L logic. A logical 1 activates the inhibit function.

DC Gate Current Mode for the CA3058 and CA3059

Connecting Terminals 7 and 12 disables the zero-crossing detector and permits the flow of gate current on demand from the differential sensing amplifier. This mode of operation is useful when comparator operation is desired or when inductive loads are switched. Care must be exercised to avoid overloading the internal power supply when operating in this mode. A sensitive gate thyristor should be used with a resistor placed between Terminal 4 and the gate in order to limit the gate current.

For a list of RCA thyristors, see RCA Thyristor Data Bulletin, File No. 406, dated 5-75.



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid gradations are in mils (10^{-3} inch).

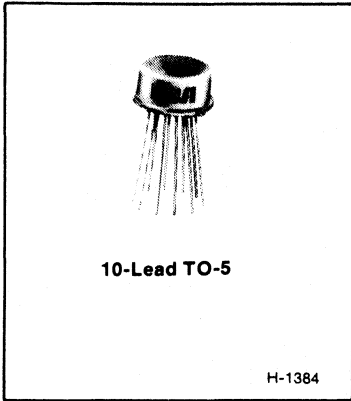
The photographs and dimensions represent a chip when it is part of the wafer. When the wafer is cut into chips, the cleavage angles are 57° instead of 90° with respect to the face of the chip. Therefore, the isolated chip is actually 7 mils (0.17 mm) larger in both dimensions.

Dimensions and pad layout for CA3059H.

Differential Amplifiers Technical Data

	Page
CA3000	562
CA3001	569
CA3004	575
CA3005	581
CA3006	581
CA3007	588
CA3026	See Page 354
CA3028	593
CA3040	604
CA3049	See Page 372
CA3050	See Page 410
CA3051	See Page 410
CA3053	593
CA3054	See Page 354
CA3102	See Page 372

CA3000



DC Amplifier

Features:

- Designed for use in Communication, Telemetry, Instrumentation, and Data-Processing Equipment
- Balanced differential-amplifier configuration with controlled constant-current source to provide outstanding versatility
- Built-in temperature stability for operation from -55°C to $+125^{\circ}\text{C}$
- Companion Application Note, ICAN 5030 "Applications of RCA CA3000 Integrated Circuit DC Amplifier" covers characteristics of different operating modes, frequency consid-

erations, 10 MHz narrow band tuned amplifier design, crystal oscillator design, and many other application aids

- Input impedance - 195 k Ω typ.
- Voltage gain - 37 dB typ.
- Common-mode rejection ratio - 98 dB typ.
- Input offset voltage - 1.4 mV typ.
- Push-pull input and output
- Frequency capability - DC to 30 MHz (with external C and R)
- Wide AGC range - 90 dB typ.

Applications

- Schmitt trigger
- RC-coupled feedback amplifier
- Mixer
- Comparator
- Modulator
- Crystal oscillator
- Sense amplifier

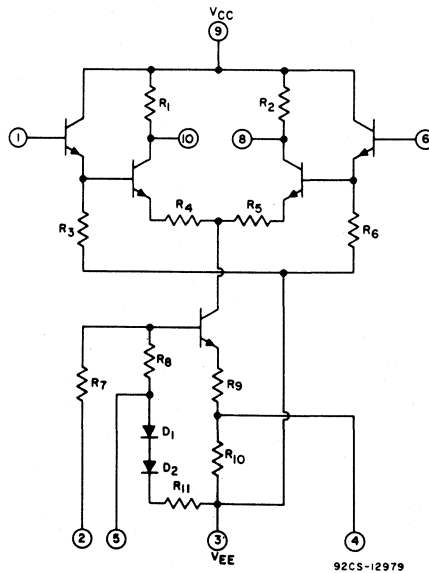


Fig. 1 - Schematic Diagram

ABSOLUTE-MAXIMUM VOLTAGE LIMITS, at $T_A = 25^\circ\text{C}$

Indicated voltage limits for each terminal can be used under specified voltage conditions for other terminals

All voltages are with respect to ground (common terminal of Positive and Negative DC Supplies)

TERMINAL	VOLTAGE LIMITS		CONDITIONS	
	NEGATIVE	POSITIVE	TERMINAL	VOLTAGE
1	-2	+2	2	0
			3	-6
			6	0
			9	+6
2	-8	0	1	0
			3	-8
			6	0
3	-10	0	1	0
			2	0
			6	0
4	-8	0	1	0
			2	0
			6	0
5	-6	0	1	0
			2	0
			3	-6
			6	0
			9	+6

TERMINAL	VOLTAGE LIMITS		CONDITIONS	
	NEGATIVE	POSITIVE	TERMINAL	VOLTAGE
6	-2	+2	1	0
			2	0
			3	-6
			9	+6
7	NO CONNECTION			
8	0	+6	1	0
			2	0
			3	-6
			6	0
9	0	+10	1	0
			2	0
			3	-6
			6	0
10	0	+6	1	0
			2	0
			3	-6
			6	0
CASE	Internally Connected to Terminal No.3 (Substrate) DO NOT GROUND			

OPERATING-TEMPERATURE RANGE -55°C to $+125^\circ\text{C}$
 STORAGE-TEMPERATURE RANGE -65°C to $+150^\circ\text{C}$
 LEAD TEMPERATURE (During Soldering):
 At distance $1/16 \pm 1/32$ inch ($1.59 \pm 0.79\text{mm}$) $+265^\circ\text{C}$
 from case for 10 seconds max.
 MAXIMUM SINGLE-ENDED INPUT-SIGNAL VOLTAGE $\pm 4\text{ V}$
 MAXIMUM COMMON-MODE INPUT-SIGNAL VOLTAGE $\pm 2\text{ V}$
 MAXIMUM DEVICE DISSIPATION:
 From -55°C to 85°C 450
 Above 85°C Derate $5\text{ mW}/^\circ\text{C}$

Linear Integrated Circuits

CA3000

ELECTRICAL CHARACTERISTICS, at $T_A = 25^\circ\text{C}$, $V_{CC} = +6\text{V}$, $V_{EE} = -6\text{V}$, unless otherwise specified

CHARACTERISTICS	SYMBOLS	SPECIAL TEST CONDITIONS Terminals No.4 & No.5 Not Connected Unless Specified	LIMITS					TYPICAL CHARAC- TERISTICS CURVES
			TEST CIRCUITS	TYPE CA3000				
				Fig.	Min.	Typ.	Max.	
STATIC CHARACTERISTICS								
Input Offset Voltage	V_{IO}			-	1.4	5	mV	2
Input Offset Current	I_{IO}			-	1.2	10	μA	2
Input Bias Current	I_{IB}			-	23	36	μA	3
Quiescent Operating Voltage	V_8 or V_{IO}	TERMINALS						
		4	5					
		NC	NC	-	2.6	-	V	4
		NC	VEE	-	4.2	-	V	4
		VEE	NC	-	-1.5	-	V	4
		VEE	VEE	-	0.6	-	V	4
Device Dissipation	P_D	NC	NC	-	30	-	mW	NONE
DYNAMIC CHARACTERISTICS								
Differential Voltage Gain Single-Ended Input	A_{DIFF}	Single-Ended Output $f = 1 \text{ kHz}$	9	28	32	-	dB	5
		Double-Ended Output $f = 1 \text{ kHz}$	9	-	38	-	dB	5
Bandwidth at -3 dB Point	BW	$V_I = 10 \text{ mV}$, $R_S = 1 \text{ k}\Omega$		-	650	-	kHz	7
Maximum Output Voltage Swing	$V_{OUT(P-P)}$	$f = 1 \text{ kHz}$	9	-	6.4	-	V(P-P)	NONE
Common-Mode Rejection Ratio	CMRR	$f = 1 \text{ kHz}$	13	70	98	-	dB	8
Single-Ended Input Impedance	Z_{IN}	$f = 1 \text{ kHz}$	15	70K	195K	-	Ω	10
Single-Ended Output Impedance	Z_{OUT}	$f = 1 \text{ kHz}$	17	5.5K	8K	10.5K	Ω	12
Total Harmonic Distortion	THD	$R_S = 1 \text{ k}\Omega$ $f = 1 \text{ kHz}$ $V_O = 42 \text{ V}_{P-P}$		-	0.2	5	%	14
AGC Range (Maximum Voltage Gain to Complete Cutoff)	AGC	$f = 1 \text{ kHz}$	20	80	90	-	dB	NONE

STATIC CHARACTERISTICS

INPUT OFFSET VOLTAGE AND CURRENT vs TEMPERATURE

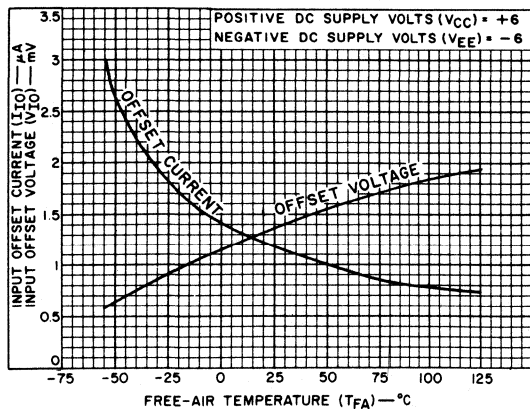


Fig.2

INPUT BIAS CURRENT vs TEMPERATURE

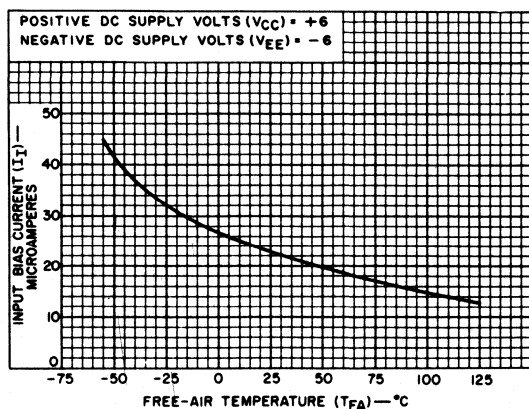


Fig.3

STATIC CHARACTERISTICS

QUIESCENT OPERATING VOLTAGE vs TEMPERATURE

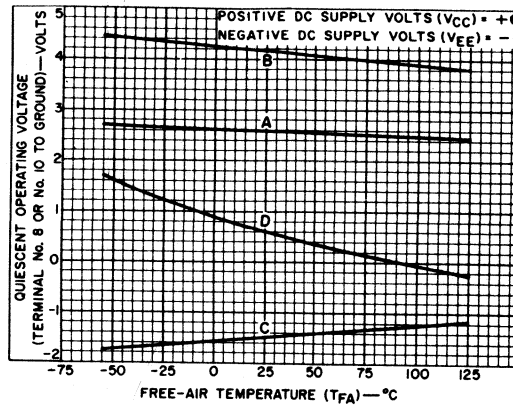


Fig. 4

DYNAMIC CHARACTERISTICS AND TEST CIRCUIT FOR TYPE CA3000

DIFFERENTIAL VOLTAGE GAIN vs TEMPERATURE

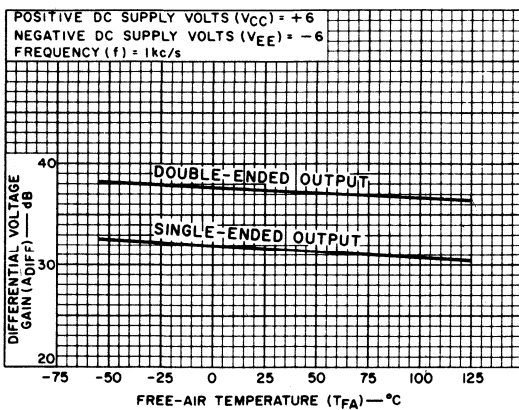


Fig. 5

DIFFERENTIAL VOLTAGE GAIN AND MAXIMUM OUTPUT VOLTAGE SWING TEST CIRCUIT

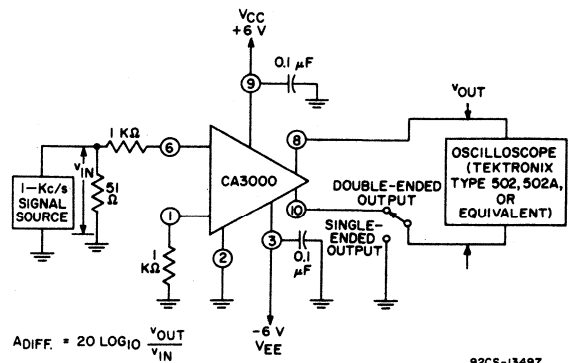


Fig. 6

DYNAMIC CHARACTERISTICS AND TEST CIRCUIT

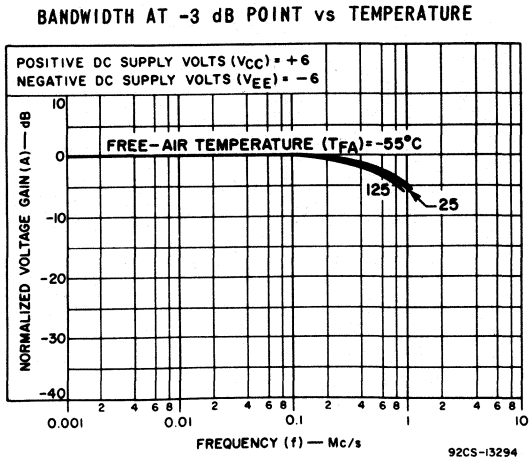


Fig. 7

COMMON-MODE REJECTION RATIO vs TEMPERATURE

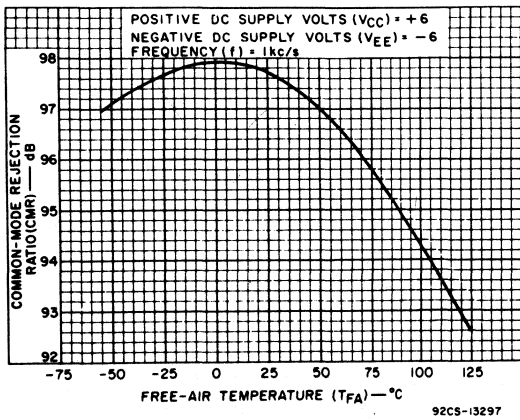
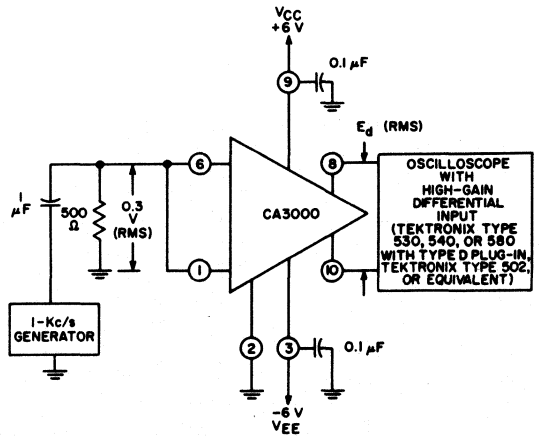


Fig. 8

COMMON-MODE REJECTION RATIO TEST CIRCUIT



COMMON-MODE REJECTION RATIO (CMR) = $20 \log \frac{(A^*)(2)(0.3)}{E_d \text{ (RMS)}}$

*A = SINGLE-ENDED VOLTAGE GAIN

92CS-12983RI

Fig. 9

DYNAMIC CHARACTERISTICS AND TEST CIRCUITS FOR TYPE CA3000

SINGLE-ENDED INPUT IMPEDANCE vs TEMPERATURE

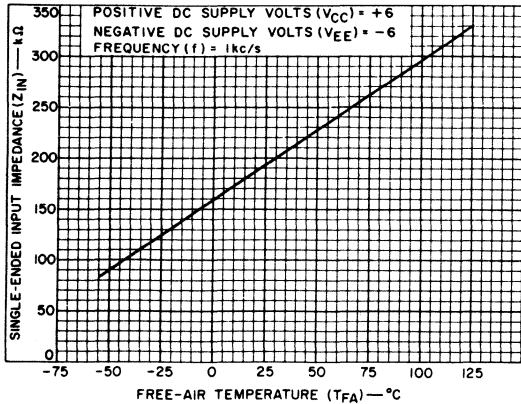


Fig. 10

SINGLE-ENDED INPUT IMPEDANCE TEST CIRCUIT

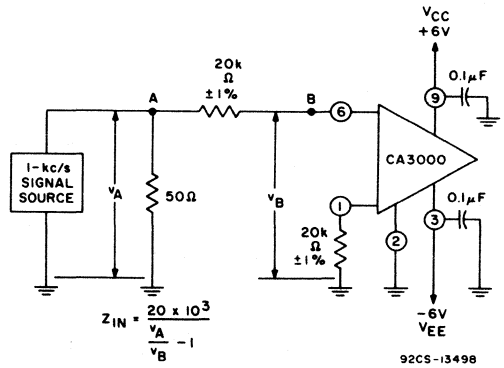


Fig. 11

SINGLE-ENDED OUTPUT IMPEDANCE vs TEMPERATURE

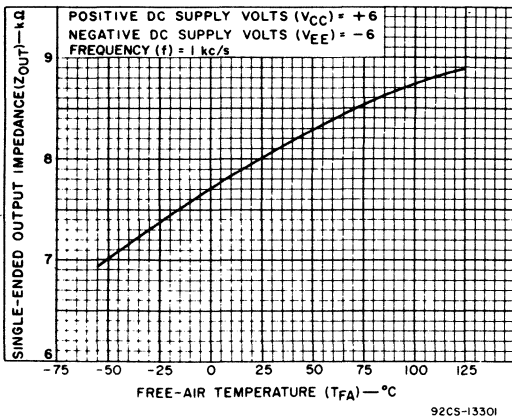
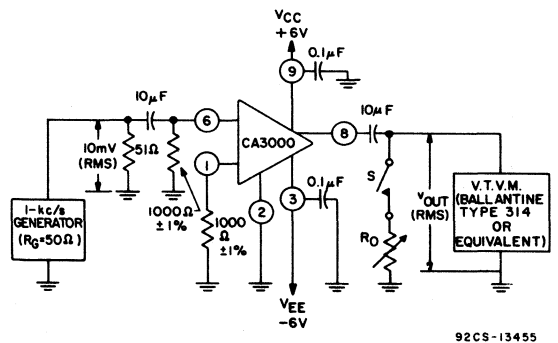


Fig. 12

SINGLE-ENDED OUTPUT IMPEDANCE TEST CIRCUIT



1. With Switch S open, record reference voltage $V_{OUT}(rms)$.
2. Close Switch S, and adjust R_O until

$$V_{OUT} = \frac{\text{Reference Voltage}}{2}$$
3. Record value of R_O as Z_{OUT} .

Fig. 13

DYNAMIC CHARACTERISTICS AND TEST CIRCUIT

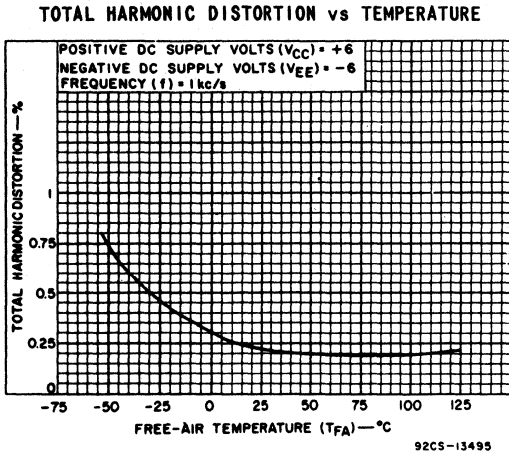
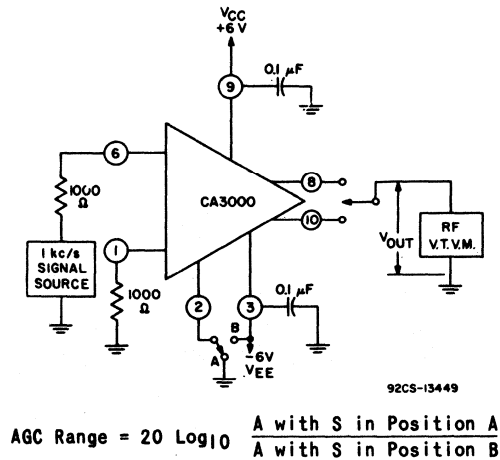


Fig. 14

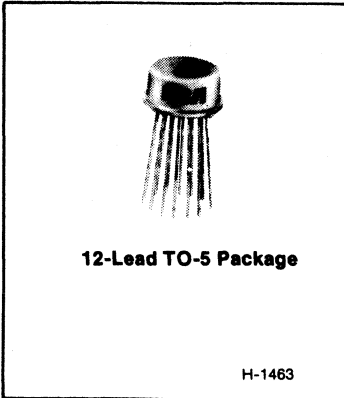
AGC RANGE TEST CIRCUIT



$$\text{AGC Range} = 20 \text{ Log}_{10} \frac{\text{A with S in Position A}}{\text{A with S in Position B}}$$

Fig. 15

Video and Wide-band Amplifier



Features:

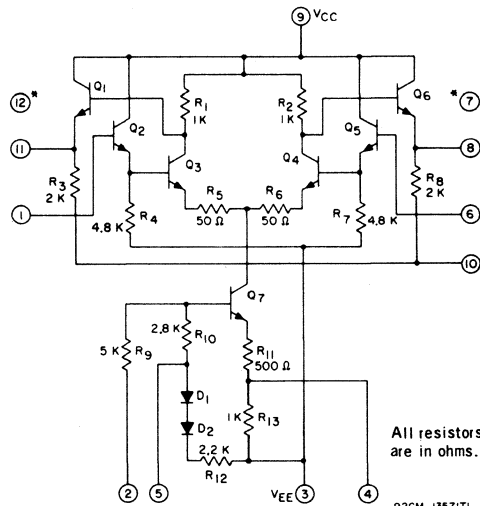
- Designed for use in video systems and communication equipment
- Balanced differential amplifier configuration with controlled constant-current source provides outstanding versatility
- Built-in temperature stability for operation from -55° C to +125° C
- Emitter follower input & output
- Companion Application Note ICAN5038 "Application of the RCA-CA3001 Integrated-Circuit Video

Amplifier", covers different operating modes, gain control, distortion, swing capability, 3 stage amplifier design, and a Schmitt trigger study.

- Push-pull input & output
- AGC range - 60 dB typ.
- Bandwidth - 29 MHz
- Input resistance - 150 kΩ typ.
- Output resistance - 45 Ω typ.
- Voltage gain - 19 dB typ.
- Input offset voltage - 1.5 mV typ.

Applications

- Schmitt trigger
- Mixer
- Modulator
- DC, IF & video amplifier



* Internal Connection - DO NOT USE

Fig. 1 - Schematic Diagram.

Linear Integrated Circuits

CA3001

ABSOLUTE-MAXIMUM VOLTAGE AND CURRENT LIMITS at $T_A = 25^\circ\text{C}$

Indicated voltage or current limits for each terminal can be applied under the specified conditions for other terminals.

All Voltages are with respect to ground (common terminal of Positive and Negative DC Supplies).

TERMINAL	VOLTAGE OR CURRENT LIMITS		CONDITIONS	
	NEGATIVE	POSITIVE	TERMINAL	VOLTAGE
1	-2.5	+2.5	2, 6 3, 10 9	0 -6 +6
2	-8.5	0	1, 6 3, 10 9	0 -8.5 +6
3	-10	0	1, 2, 6 9 10	0 +6 -6
4	-8.5	0	1, 2, 6 9 10	0 +6 -6
5	-6	0	1, 2, 6 3, 10 9	0 -6 +6
6	-2.5	+2.5	1, 2 3, 10 9	0 -6 +6
7	INTERNAL CONNECTION DO NOT USE			

TERMINAL	VOLTAGE OR CURRENT LIMITS		CONDITIONS	
	NEGATIVE	POSITIVE	TERMINAL	VOLTAGE
8	25 mA		1, 2, 6, 10 3 9	0 -6 +6
			200- Ω RESISTOR CONNECTED BETWEEN TERMINALS No.8 & No.10	
9	0	+10	1, 2, 6, 10 3	0 -6
10	-10	0	1, 2, 6 3 9	0 -6 +6
11	25 mA		1, 2, 6, 10 3 9	0 -6 +6
			200- Ω RESISTOR CONNECTED BETWEEN TERMINALS No.10&No.11	
12	INTERNAL CONNECTION DO NOT USE			
CASE	INTERNALLY CONNECTED TO TERMINAL No.3 (SUBSTRATE) DO NOT GROUND			

OPERATING TEMPERATURE RANGE -55°C to $+125^\circ\text{C}$

STORAGE TEMPERATURE RANGE -65°C to $+150^\circ\text{C}$

LEAD TEMPERATURE (During Soldering):

At distance $1/16 \pm 1/32$ inch ($1.59 \pm 0.79\text{mm}$)

from case for 10 seconds max. $+265^\circ\text{C}$

MAXIMUM SINGLE-ENDED INPUT-SIGNAL VOLTAGE $\pm 4\text{ V}$

MAXIMUM COMMON-MODE INPUT-SIGNAL VOLTAGE $\pm 2.5\text{ V}$

MAXIMUM DEVICE DISSIPATION:

-55 to 85°C 450 mW

Above 85°C Derate linearly $5\text{ mW}/^\circ\text{C}$

ELECTRICAL CHARACTERISTICS, AT $T_A = 25^\circ\text{C}$, $V_{CC} = +6\text{V}$, $V_{EE} = -6\text{V}$

CHARACTERISTICS (See Page 2 for Definitions of Terms)	SYMBOLS	SPECIAL TEST CONDITIONS Terminals No.4 and No.5 Not Connected Unless Specified	TEST CIRCUITS	LIMITS				TYPICAL CHARAC- TERISTICS CURVES		
				TYPE CA3001						
				Fig.	Min.	Typ.	Max.		Units	Fig.
STATIC CHARACTERISTICS:										
Input Offset Voltage	V_{IO}		4	-	1.5	-	mV	2		
Input Offset Current	I_{IO}		5	-	1	10	μA	2		
Input Bias Current	I_I		5	-	16	36	μA	3		
Output Offset Voltage	V_{OO}	$R_S = 1\text{ k}\Omega$		-	54	300	mV	6		
Quiescent Operating Voltage	V_8 OR V_{11}	TERMINALS								
		MODE	4	5						
		A	NC	NC		3.8	4.4	5	V	7
		B	NC	V_{EE}		-	4.8	-	V	7
		C	V_{EE}	NC		-	2.7	-	V	7
Device Dissipation	P_D	A	NC	NC		60	78	120	mW	8
		B	NC	V_{EE}		-	71	-	mW	8
		C	V_{EE}	NC		-	110	-	mW	8
		D	V_{EE}	V_{EE}		-	86	-	mW	8
DYNAMIC CHARACTERISTICS:										
Differential Voltage Gain (Single-ended input and output)	A_{DIFF}	$f = 1.75\text{ MHz}$		16	19	-	dB	9 A, 9, B		
		$f = 20\text{ MHz}$		10	14	-	dB	9 B		
Bandwidth at -3 dB Point	BW	$R_S = 50\Omega$		16	29	-	MHz	NONE		
Maximum Output Voltage Swing	$V_{OUT(P-P)}$	$R_S = 50\Omega$, $f = 1.75\text{ MHz}$		-	5	-	V _{p-p}	NONE		
Noise Figure	NF	$f = 1.75\text{ MHz}$, $R_S = 1\text{ k}\Omega$	14	-	5	8	dB	10		
		$f = 11.7\text{ MHz}$, $R_S = 1\text{ k}\Omega$	14	-	7.7	-	dB	10		
Common-Mode Rejection Ratio	CMRR	$f = 1\text{ KHz}$	16	70	88	-	dB	12		
Input Impedance Components:										
Parallel Input Resistance	R_{IN}	$f = 1.75\text{ MHz}$		50	140	-	$\text{k}\Omega$	14		
Parallel Input Capacitance	C_{IN}	$f = 1.75\text{ MHz}$		-	3.4	7	pF	14		
Output Resistance	R_{OUT}	$f = 1.75\text{ MHz}$		-	45	70	Ω	NONE		
AGC Range (Maximum voltage gain to complete cutoff)	AGC	$f = 1.75\text{ MHz}$	19	55	60	-	dB	NONE		

TYPICAL STATIC CHARACTERISTICS

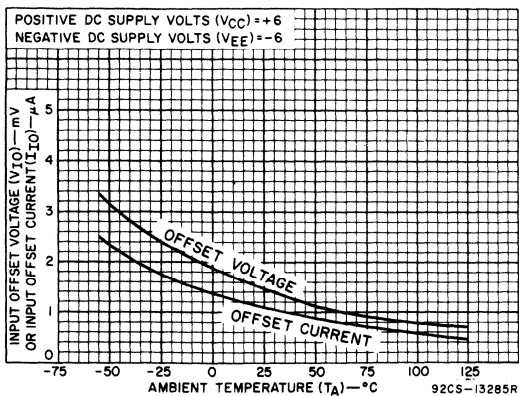


Fig.2 - Input offset voltage and current vs. temperature.

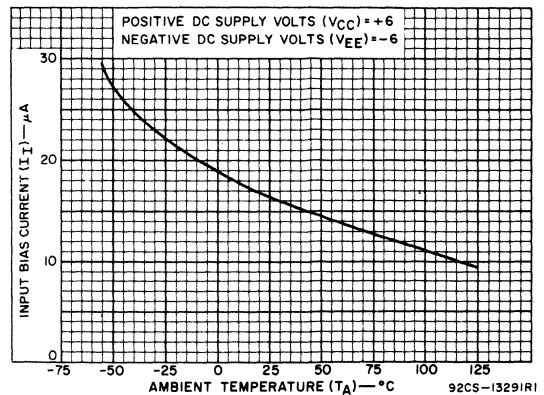
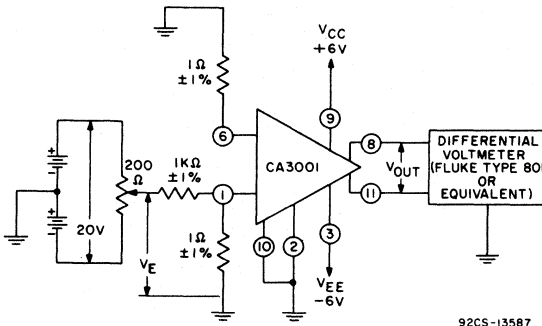


Fig.3 - Input bias current vs. temperature.

Linear Integrated Circuits

CA3001

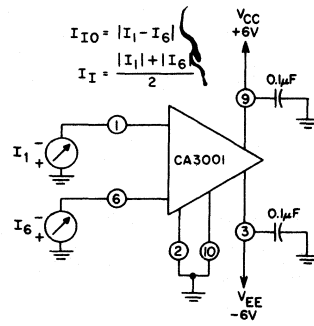
TYPICAL STATIC CHARACTERISTICS AND TEST CIRCUITS



92CS-13587

1. Adjust V_E for $V_{OUT(DC)} = 0 \pm 0.1 \text{ V}$
2. Measure V_E and record input offset voltage (V_{IO}) in mV as
$$V_{IO} = \frac{V_E}{1000}$$

Fig. 4 - Input offset voltage test circuit.



92CS-13556

Fig. 5 - Input offset current and input bias current test circuit.

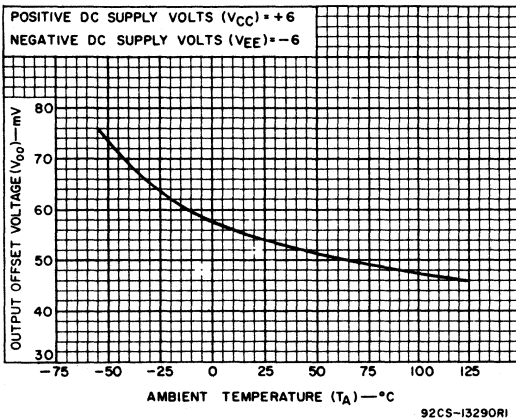


Fig. 6 - Output offset voltage vs. temperature.

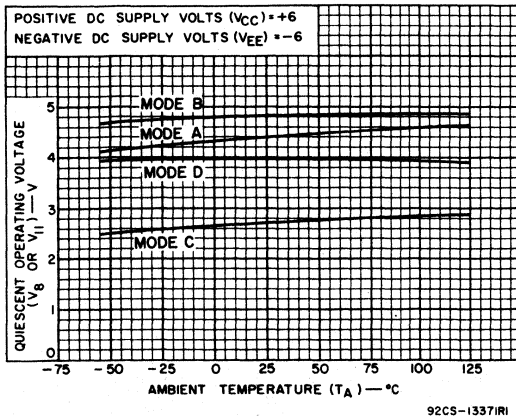


Fig. 7 - Quiescent operating voltage vs. temperature.

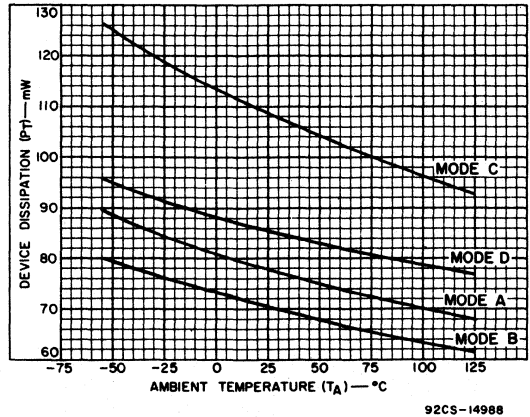


Fig. 8 - Device dissipation vs. temperature.

TYPICAL DYNAMIC CHARACTERISTICS

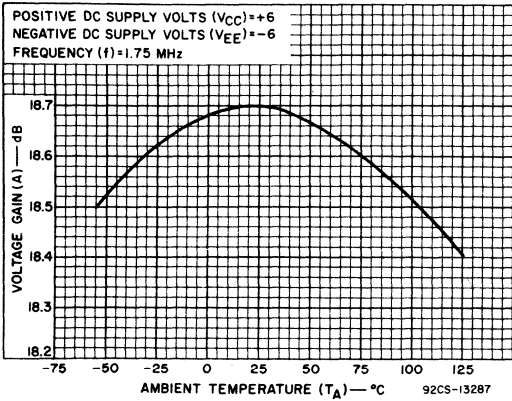


Fig.9 a - Differential voltage gain vs. temperature.

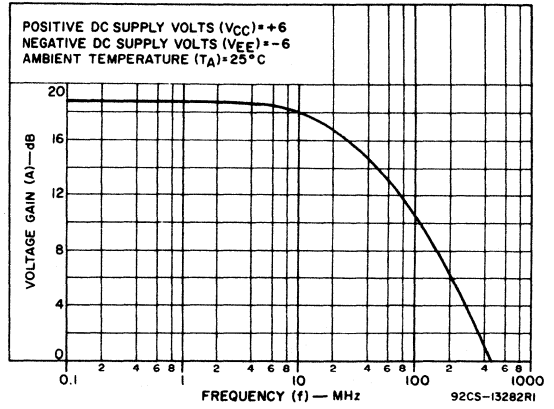


Fig.9 b - Differential voltage gain vs. frequency.

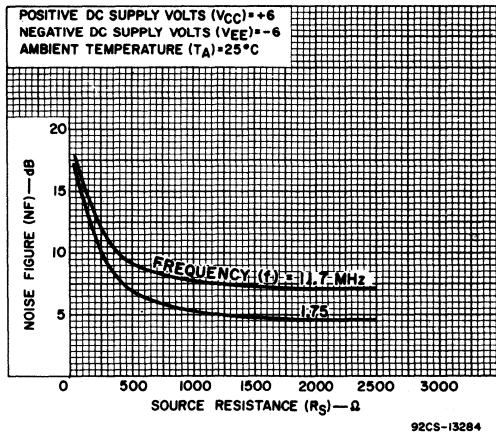
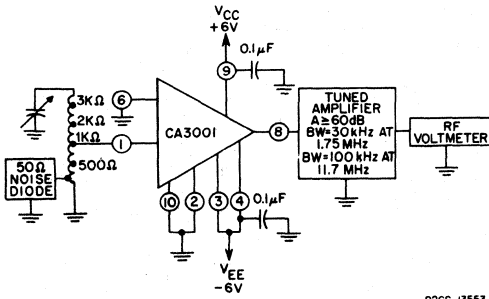


Fig.10 - Noise figure vs. source resistance and frequency.

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CA3001

TYPICAL DYNAMIC CHARACTERISTICS AND TEST CIRCUITS



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* Separate tuned input circuits are used for 1.75 MHz and 11.7 MHz. Source-resistance matching taps adjusted with circuit tuned to resonance and with 50-ohm resistor connected to simulate noise diode.

Fig. 11 - Noise figure test circuit.

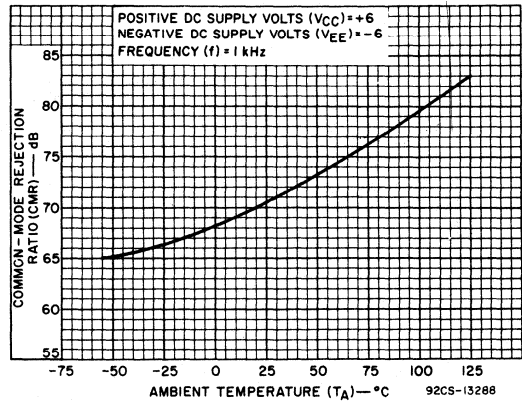
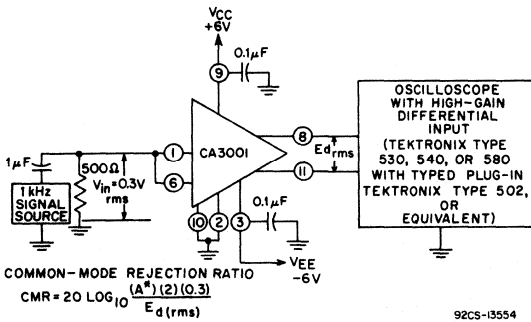


Fig. 12 - Common-mode rejection ratio vs. temperature.



92CS-13554

* A = SINGLE-ENDED VOLTAGE GAIN

Fig. 13 - Common-mode rejection ratio test circuit.

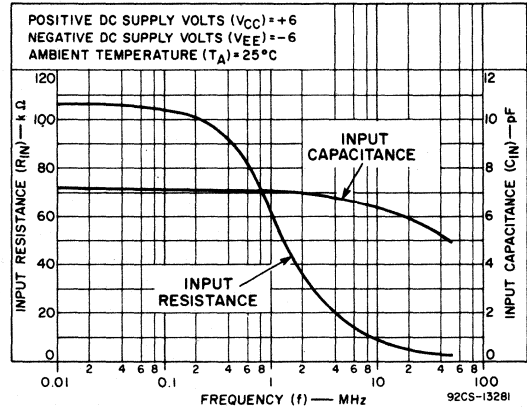
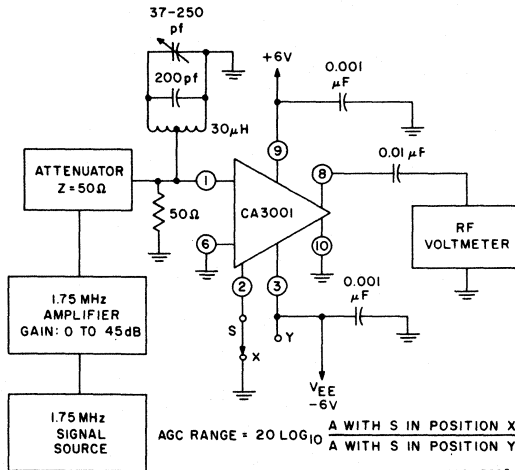
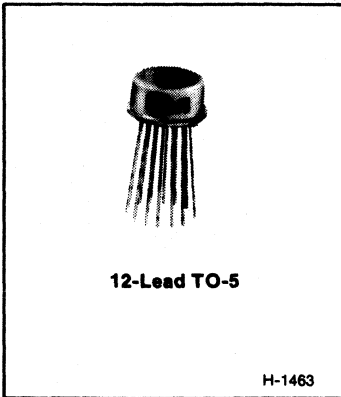


Fig. 14 - Input impedance components vs. frequency.



92CS-13586

Fig. 15 - AGC range test circuit.



RF Amplifier

Features:

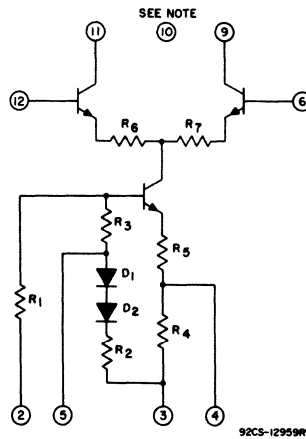
- Designed for use in communications equipment
- Balanced differential-amplifier configuration with controlled constant-current source provides unexcelled versatility
- Built-in temperature stability for operation from -55°C to $+125^{\circ}\text{C}$
- Similar to RCA CA3005 and CA3006, plus emitter-degeneration resistors to provide more linear

transfer characteristic and increased input-signal handling capability

- Companion Application Note ICAN 5022 "Application of RCA CA3004, CA3005, and CA3006 Integrated Circuit RF Amplifiers", covers characteristics of different operating modes, noise performance, cross-modulation, mixer, AGC, limiter, detector, and amplifier design considerations.

Applications:

- Push-pull input and output
- Wide and narrow-band amplifier
- AGC
- Detector
- Operation from DC to 100 MHz
- Mixer
- Limiter
- Modulator
- RF, IF and video frequency capability



NOTE: Connect Terminal No. 10 to most positive dc supply voltage used for circuit.

Fig. 1 — Schematic Diagram for CA3004

Linear Integrated Circuits

CA3004

ABSOLUTE-MAXIMUM VOLTAGE LIMITS, at $T_{FA} = 25^{\circ}C$

Voltage limits shown for each terminal can be applied under the indicated circuit conditions for other terminals.

All voltages are with respect to GROUND (common terminal of Positive and Negative DC Supplies)

TERMINAL	VOLTAGE LIMITS		CONDITIONS	
	NEGATIVE	POSITIVE	TERMINAL	VOLTAGE
1	NO CONNECTION			
2	-9.5	0	6	0
			12	0
			3	-9.5
			9	+6
			10	+6
3	-12	0	2	0
			6	0
			9	+6
			10	+6
			11	+6
4	-12	0	2	0
			6	0
			9	+6
			10	+6
			11	+6
5	-6	0	2,6,12	0
			3	-6
			9	+6
			10	+6
			11	+6
6	-3.5	+3.5	2	0
			3	-6
			9	+6
			10	+6
			11	+6
12	0			

TERMINAL	VOLTAGE LIMITS		CONDITIONS	
	NEGATIVE	POSITIVE	TERMINAL	VOLTAGE
7	NO CONNECTION			
8	NO CONNECTION			
9	0	+12	2	0
			3	-6
			6	0
			10	+6
			11	+6
10	0	+12	2	0
			3	-6
			6	0
			9	+6
			11	+6
11	0	+12	2	0
			3	-6
			6	0
			10	+6
			11	+6
12	-3.5	+3.5	2	0
			3	-6
			6	0
			9	+6
			10	+6
11	+6			
CASE	INTERNALLY CONNECTED TO TERMINAL NO.3 (SUBSTRATE) DO NOT GROUND			

OPERATING-TEMPERATURE RANGE $-55^{\circ}C$ to $+125^{\circ}C$

STORAGE-TEMPERATURE RANGE $-65^{\circ}C$ to $+150^{\circ}C$

LEAD TEMPERATURE (During Soldering)

At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm)

from case for 10 seconds max. $+265^{\circ}C$

MAXIMUM SINGLE-ENDED INPUT-

SIGNAL VOLTAGE ± 3.5 V

MAXIMUM COMMON-MODE INPUT-

SIGNAL VOLTAGE -2.5 V, $+3.5$ V

MAXIMUM DEVICE DISSIPATION 300 mW

ELECTRICAL CHARACTERISTICS, at $T_{FA} = 25^{\circ}C$, $V_{CC} = +6V$, $V_{EE} = -6V$ unless otherwise specified

CHARACTERISTICS	SYMBOLS	SPECIAL TEST CONDITIONS Terminals No.4 and No.5 Open Unless Otherwise Specified	TEST CIRCUIT	LIMITS				TYPICAL CHARAC- TERISTICS CURVES	
				TYPE CA3004					
			Fig.	Min.	Typ.	Max.	Units	Fig.	
STATIC CHARACTERISTICS									
Input Offset Voltage	V_{IO}		Fig.4	-	1.7	5	mV	Fig.2	
Input Offset Current	I_{IO}		Fig.5	-	0.125	5	μA	Fig.2	
Input Bias Current	I_I		Fig.5	-	21	40	μA	Fig.3	
Quiescent Operating Current	I_Q or I_{I1}	TERMINALS		Fig.8	-	1	-	mA	Fig.6
		4	5						
		NC	NC						
		V_{EE}	NC						
		NC	V_{EE}						
V_{EE}	V_{EE}	Fig.8	-	2.7	-	mA	Fig.6		
		NC	V_{EE}	Fig.8	-	0.45	-	mA	Fig.6
		V_{EE}	V_{EE}	Fig.8	-	1.25	-	mA	Fig.6
Quiescent Operating Current Ratio	I_Q/I_{I1}		Fig.8	-	1.1	-	-	Fig.7	
Device Dissipation	P_T		Fig.8	-	26	-	mW	NONE	
DYNAMIC CHARACTERISTICS									
Power Gain	G_P	$f = 100$ Mc/s	Fig.11	10	12	-	dB	Fig.9	
Noise Figure	NF	$f = 100$ Mc/s	Fig.11	-	6.3	9	dB	Fig.10	
Common Mode Rejection Ratio	CMR	$f = 1$ Kc/s	Fig.13	-	98	-	dB	Fig.12	
AGC Range (Max. Voltage Gain to Complete Cutoff)	AGC	$f = 1.75$ Mc/s	Fig.14	-60	-	-	dB	NONE	

DEFINITIONS OF TERMS

Input Offset Voltage

The difference in the dc voltages which must be applied to the input terminals to obtain equal quiescent operating voltages (zero output offset voltage) at the output terminals.

Input Offset Current

The difference in the currents at the two input terminals when the quiescent operating voltages at the two output terminals are equal.

Input Bias Current

The average value (one-half the sum) of the currents at the two input terminals when the quiescent operating voltages at the two output terminals are equal.

Quiescent Operating Current

The average (dc) value of the current in either output terminal.

Quiescent Operating Current Ratio

The ratio of the Quiescent operating currents in the two output terminals.

Device Dissipation

The total power drain of the device with no signal applied and no external load current.

Power Gain

The ratio of the signal power developed at the output of the device to the signal power applied to the input, expressed in dB.

Noise Figure

The ratio of the total noise power of the device and a resistive signal source to the noise power of the signal source alone, the signal source representing a generator of zero impedance in series with the source resistance.

Common-Mode Rejection Ratio

The ratio of the full differential voltage gain to the common-mode voltage gain.

Common-Mode Voltage Gain

The ratio of the signal voltages developed between the two output terminals to the signal voltage applied to the two input terminals connected in parallel for ac.

Differential Voltage Gain

The ratio of the change in output voltage at either output terminal with respect to ground, to a change in input voltage at either input terminal with respect to ground, with the other input terminal at ac ground.

AGC Range

The total change in voltage gain (from maximum gain to complete cutoff) which may be achieved by application of the specified range of dc voltage to the AGC input terminal of the device.

CA3004

TYPICAL STATIC CHARACTERISTICS AND TEST CIRCUITS FOR TYPE CA3004

INPUT OFFSET VOLTAGE AND CURRENT VS TEMPERATURE

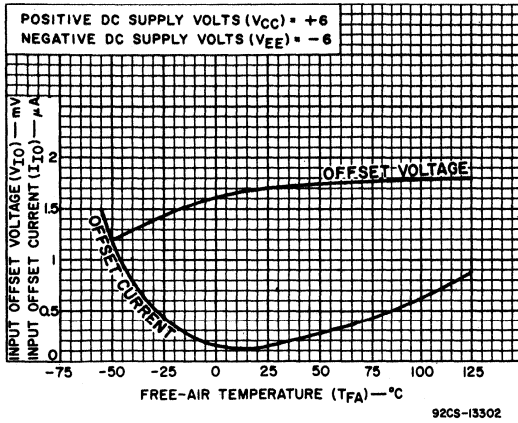


Fig.2

INPUT BIAS CURRENT VS TEMPERATURE

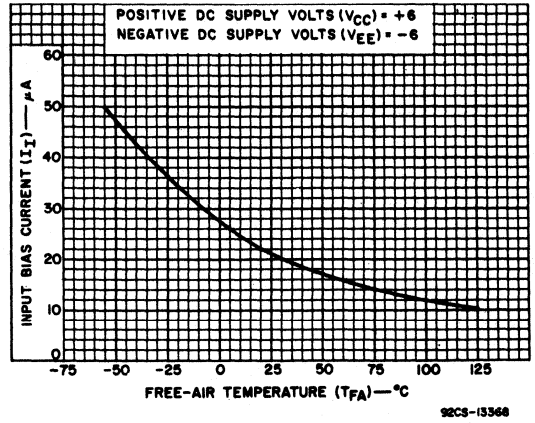


Fig.3

INPUT OFFSET VOLTAGE TEST CIRCUIT

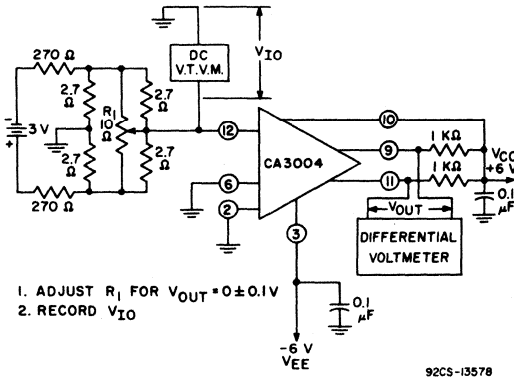


Fig.4

INPUT OFFSET CURRENT AND BIAS CURRENT TEST CIRCUIT

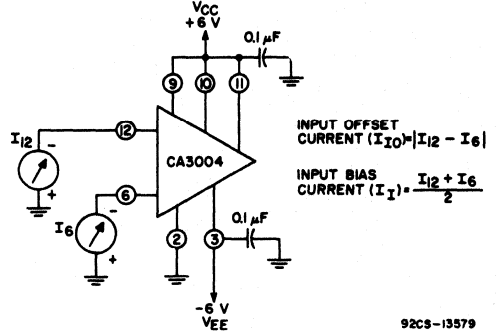


Fig.5

QUIESCENT OPERATING CURRENT VS TEMPERATURE

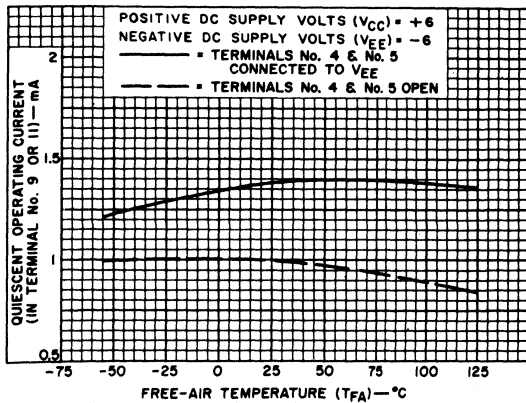


Fig.6

QUIESCENT OPERATING CURRENT RATIO VS TEMPERATURE

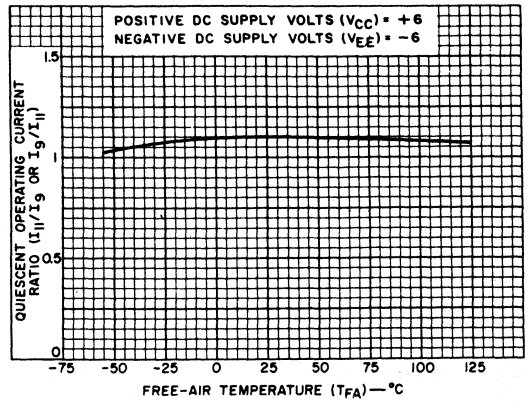
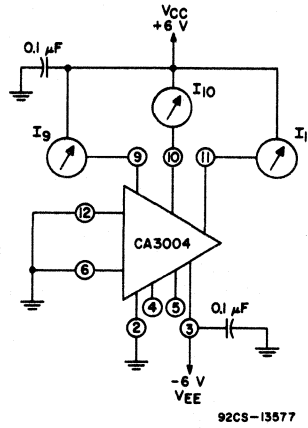


Fig.7

TEST CIRCUIT FOR TYPE CA3004

QUIESCENT OPERATING CURRENT, QUIESCENT OPERATING CURRENT RATIO, AND DEVICE DISSIPATION TEST CIRCUIT



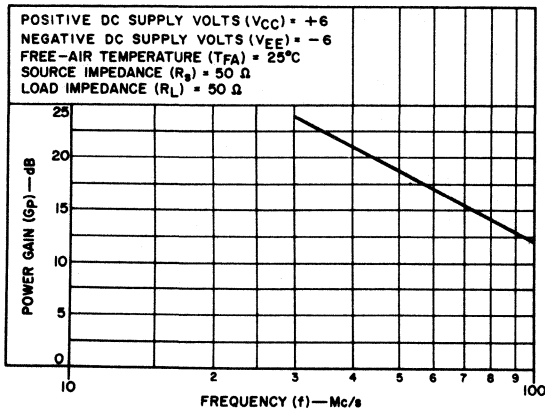
92CS-13577

$$P_T = V_{CC} (I_9 + I_{10} + I_{11}) + V_{EE} I_3$$

Fig.8

TYPICAL DYNAMIC CHARACTERISTICS FOR TYPE CA3004

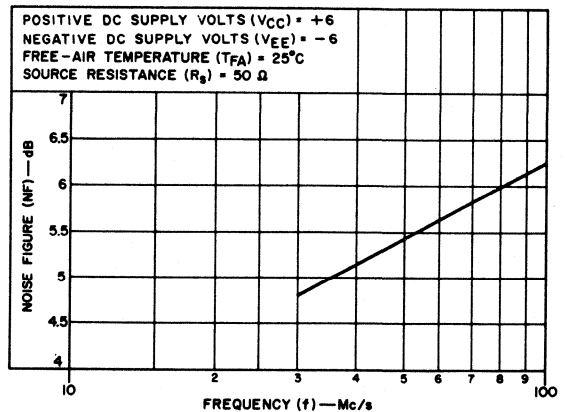
POWER GAIN VS FREQUENCY



92CS-13369

Fig.9

NOISE FIGURE VS FREQUENCY



92CS-13370

Fig.10

Linear Integrated Circuits

CA3004

TYPICAL DYNAMIC CHARACTERISTICS AND TEST CIRCUITS FOR TYPE CA3004

100 Mc/s POWER GAIN AND NOISE FIGURE TEST CIRCUIT

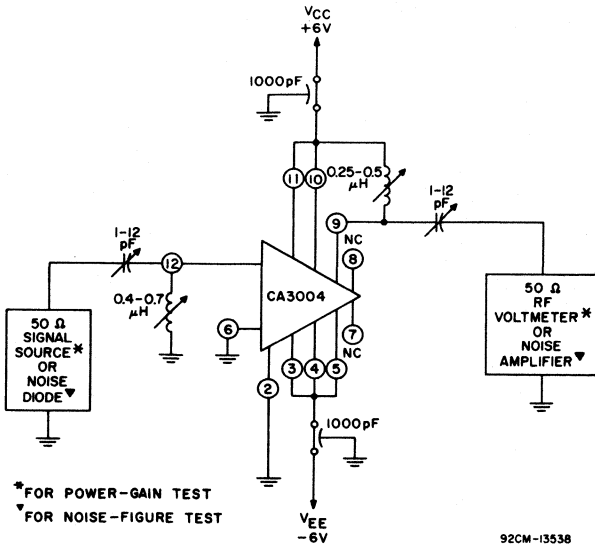


Fig. 11

COMMON-MODE REJECTION RATIO VS TEMPERATURE

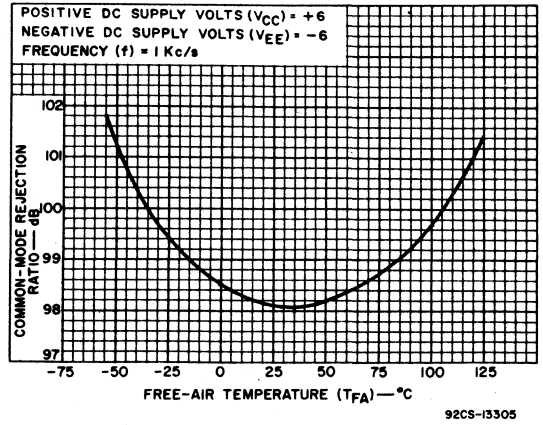


Fig. 12

COMMON-MODE REJECTION RATIO TEST CIRCUIT

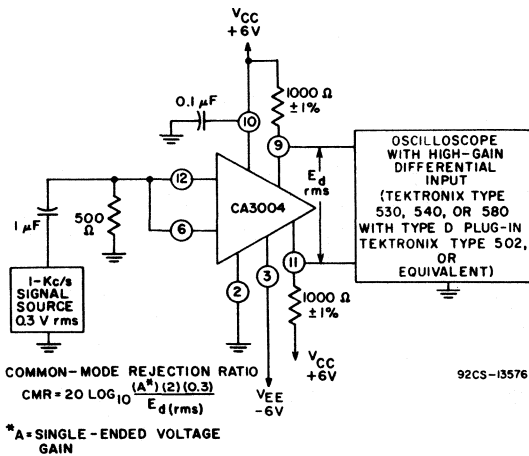


Fig. 13

AGC RANGE TEST CIRCUIT

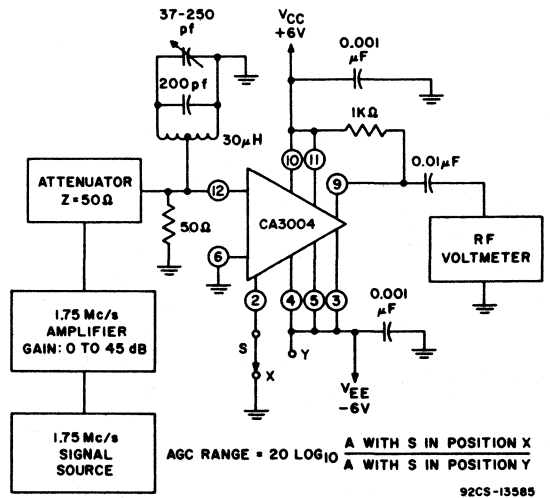
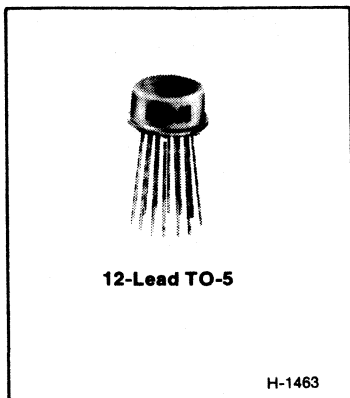


Fig. 14

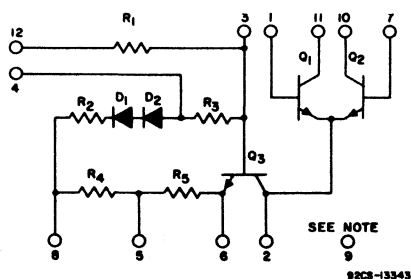
RF Amplifiers



Features:

- Designed for use in communications equipment
- Balanced differential amplifier configuration with controlled constant-current source to provide unexcelled versatility
- Built-in temperature stability for operation from -55°C to $+125^{\circ}\text{C}$
- Companion Application Note, ICAN 5022 "Application of RCA CA3004,

CA3005, and CA3006 Integrated Circuit RF Amplifiers", covers characteristics of different operating modes, noise performance, cross-modulation, mixer, AGC limiter, detector, and amplifier design considerations.



NOTE: Connect Terminal No.9 to most positive dc supply voltage used for circuit.

Applications:

- Push-pull input and output
- Wide and narrow band amplifier
- AGC
- Detector
- RF, IF, and video frequency capability
- Operation from DC to 100 MHz
- Mixer
- Limiter
- Modulator
- Cascade Amplifier

Fig. 1 — Schematic Diagram for CA3005 and CA3006.

Linear Integrated Circuits

CA3005, CA3006

ABSOLUTE-MAXIMUM VOLTAGE LIMITS, at $T_{FA} = 25^{\circ}\text{C}$

Voltage limits shown for each terminal can be applied under the indicated voltage conditions for other terminals.

All voltages are with respect to GROUND (common terminal of Positive and Negative DC Supplies)

TERMINAL	VOLTAGE LIMITS		CONDITIONS	
	NEGATIVE	POSITIVE	TERMINAL	VOLTAGE
1	-3.5	+3.5	7	0
			8	-6
			9	+6
			10	+6
			11	+6
			12	0
2	TEST POINT: DO NOT APPLY VOLTAGE FROM EXTERNAL SOURCE			
3	-9.5	0	1	0
			7	0
			8	-9.5
			9	+6
			10	+6
			11	+6
4	-6	0	1	0
			7	0
			8	-6
			9	+6
			10	+6
			11	+6
5	-12	0	1	0
			7	0
			9	+6
			10	+6
			11	+6
			12	0
6	-6	0	1	0
			7	0
			9	+6
			10	+6
			11	+6
			12	-6
7	-3.5	+3.5	1	0
			8	-6
			9	+6
			10	+6
			11	+6
			12	0

TERMINAL	VOLTAGE LIMITS		CONDITIONS	
	NEGATIVE	POSITIVE	TERMINAL	VOLTAGE
8	-12	0	1	0
			7	0
			9	+6
			10	+6
			11	+6
			12	0
9	0	+12	1	0
			7	0
			8	-6
			10	+6
			11	+6
			12	0
10	0	+12	1	0
			7	0
			8	-6
			9	+6
			11	+6
			12	0
11	0	+12	1	0
			7	0
			8	-6
			9	+6
			10	+6
			12	0
12	-9.5	0	8	-9.5
			9	+6
			10	+6
			11	+6
CASE	Internally connected to Terminal No.8 (substrate) DO NOT GROUND			

OPERATING-TEMPERATURE RANGE -55°C to $+125^{\circ}\text{C}$

STORAGE-TEMPERATURE RANGE -65°C to $+150^{\circ}\text{C}$

LEAD TEMPERATURE (During Soldering)

At distance $1/16 \pm 1/32$ inch ($1.59 \pm 0.79\text{mm}$)

from case for 10 seconds max. $+265^{\circ}\text{C}$

MAXIMUM SINGLE-ENDED INPUT-

SIGNAL VOLTAGE ± 3.5 V

MAXIMUM COMMON-MODE INPUT-

SIGNAL VOLTAGE -2.5 V, $+3.5$ V

MAXIMUM DEVICE DISSIPATION 300 mW

Differential Amplifiers

CA3005, CA3006

ELECTRICAL CHARACTERISTICS, at $T_A = 25^\circ\text{C}$, $V_{CC} = +6\text{V}$, $V_{EE} = -6\text{V}$

CHARACTERISTICS	SYMBOLS	SPECIAL TEST CONDITIONS Terminals No.3,4,5, and 6 Not Connected Except Where Noted	TEST CIRCUITS	LIMITS							TYPICAL CHARAC- TERISTICS CURVES	
				TYPE CA3005			TYPE CA3006			Fig.		
				Fig.	Min.	Typ.	Max.	Min.	Typ.			Max.
STATIC CHARACTERISTICS												
Input Offset Voltage	V_{IO}		Fig.3	--	2.6	5	-	0.8	1	mV	Fig.2	
Input Offset Current	I_{IO}		Fig.4	-	1.4	-	-	1.4	-	μA	Fig.2	
Input Bias Current	I_{IB}		Fig.4	-	19	40	-	19	40	μA	Fig.5	
Quiescent Operating Current	I_{10} or I_{11}	TERMINALS										
		4	5	Fig.8	-	1	-	-	1	-	mA	Fig.6
		NC	NC	Fig.8	-	2.7	-	-	2.7	-	mA	NONE
		NC	-VEE	Fig.8	-	0.45	-	-	0.45	-	mA	NONE
		-VEE	NC	Fig.8	-	1.25	-	-	1.25	-	mA	Fig.6
Quiescent Operating Current Ratio	$\frac{I_{10}}{I_{11}}$		Fig.8	-	1.05	-	-	1.05	-	-	Fig.7	
Device Dissipation	P_T		Fig.8	-	26	-	-	26	-	mW	NONE	
DYNAMIC CHARACTERISTICS												
Power Gain	G_p	f =	Cascode Configuration	Fig.10	16	20	-	16	20	-	dB	Fig.9
		100 MHz	Differential-Ampl. Configuration	Fig.12	14	16	-	14	16	-	dB	Fig.11
Noise Figure	NF	f =	Cascode Configuration	Fig.10	-	7.8	9	-	7.8	9	dB	Fig.13
		100 MHz	Differential Ampl. Configuration	Fig.12	-	7.8	9	-	7.8	9	dB	Fig.14
Common-Mode Rejection Ratio	CMR	f = 1 kHz		Fig.16	-	101	-	-	101	-	dB	Fig.15
AGC Range (Max. Voltage Gain to Complete Cutoff)	AGC	f = 1.75 MHz		Fig.17	-60	-	-	-60	-	-	dB	NONE

Linear Integrated Circuits

CA3005, CA3006

TYPICAL STATIC CHARACTERISTICS AND TEST CIRCUITS FOR TYPES CA3005 AND CA3006

INPUT OFFSET VOLTAGE AND CURRENT

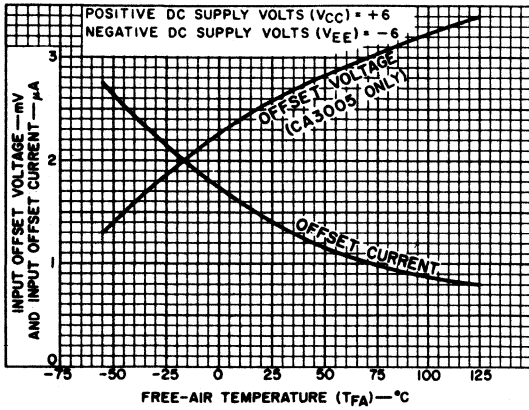


Fig. 2

INPUT OFFSET VOLTAGE TEST CIRCUIT

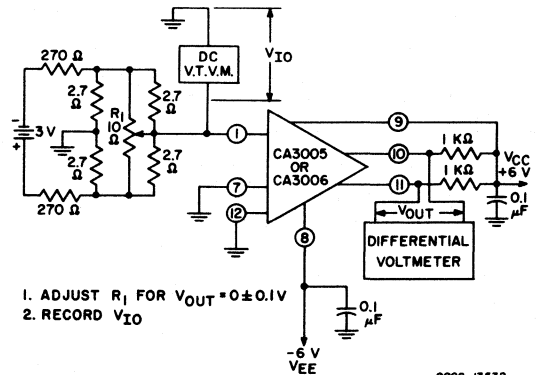


Fig. 3

INPUT BIAS CURRENT

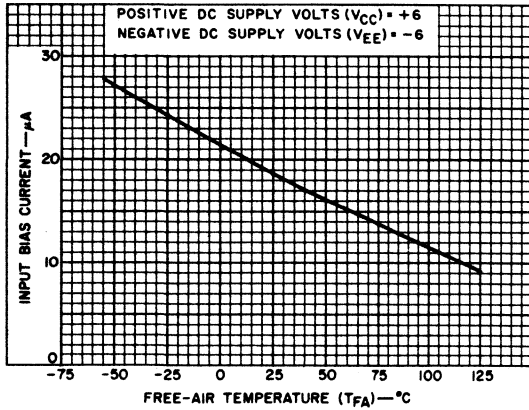


Fig. 4

QUIESCENT OPERATING CURRENT

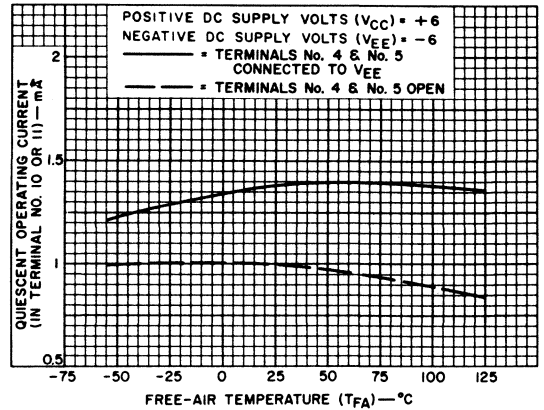


Fig. 5

QUIESCENT OPERATING CURRENT RATIO

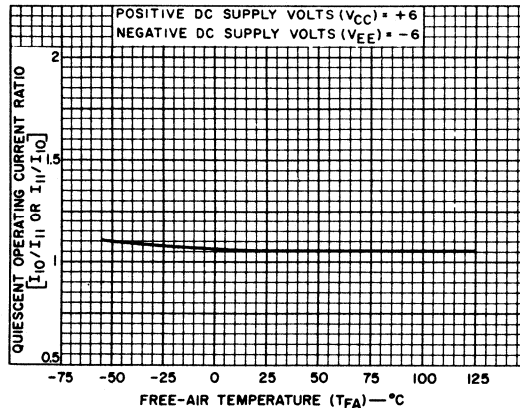


Fig. 6

TYPICAL DYNAMIC CHARACTERISTICS AND TEST CIRCUITS FOR TYPES CA3005 AND CA3006

POWER-GAIN (CASCODE CONFIGURATION)

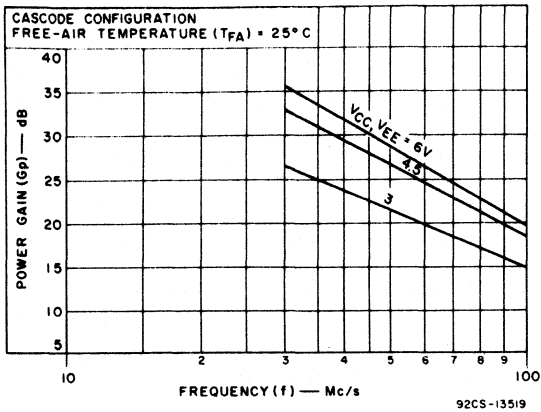


Fig. 7

POWER-GAIN (DIFFERENTIAL-AMPLIFIER CONFIGURATION)

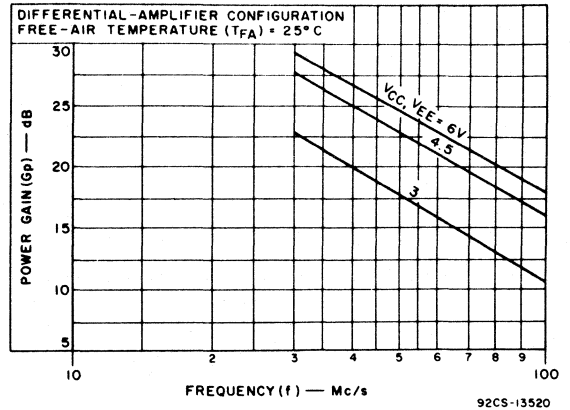
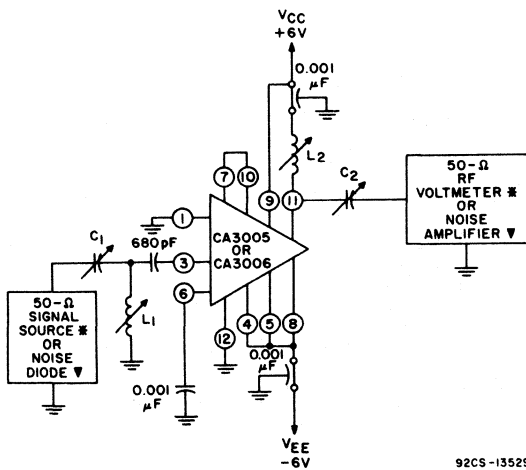


Fig. 9

NOISE FIGURE AND POWER GAIN TEST CIRCUIT (CASCODE CONFIGURATION)



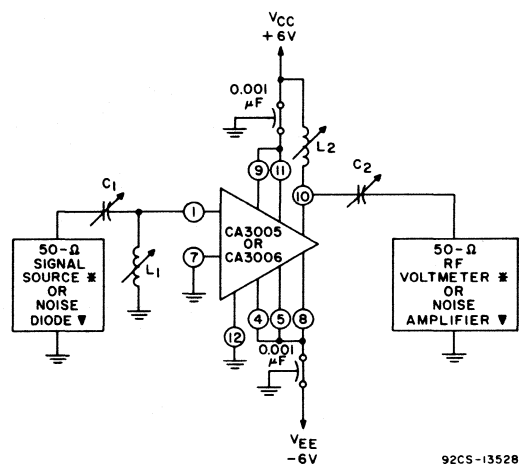
92CS-13529

f Mc/s	C ₁ pF	C ₂ pF	L ₁ μH	L ₂ μH
30	14-150	5-40	0.3-0.6	0.8-1.4
100	5-40	5-40	0.07-0.12	0.15-0.3

- * FOR POWER-GAIN TEST
- ▼ FOR NOISE-FIGURE TEST

Fig. 8

NOISE FIGURE AND POWER-GAIN TEST CIRCUIT (DIFFERENTIAL AMPLIFIER CONFIGURATION)



92CS-13528

f Mc/s	C ₁ pF	C ₂ pF	L ₁ μH	L ₂ μH
30	5-40	1.5-20	1.2-2	1.2-2
100	1-12	1-12	0.4-0.7	0.25-0.5

- * FOR POWER-GAIN TEST
- ▼ FOR NOISE-FIGURE TEST

Fig. 10

Linear Integrated Circuits

CA3005, CA3006

TYPICAL DYNAMIC CHARACTERISTICS FOR TYPES CA3005 AND CA3006

100-Mc/s NOISE FIGURE VS. V_{EE} (CASCODE CONFIGURATION)

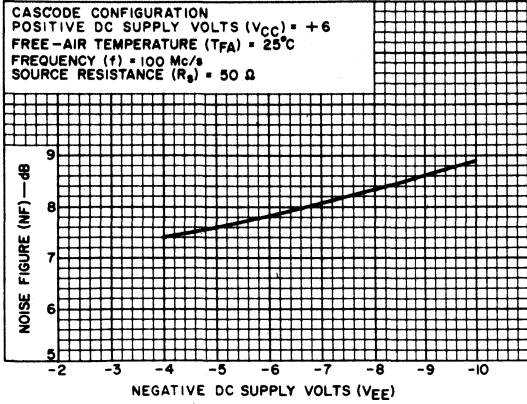


Fig. 11

100 Mc/s NOISE FIGURE VS. V_{EE} (DIFFERENTIAL AMPLIFIER CONFIGURATION)

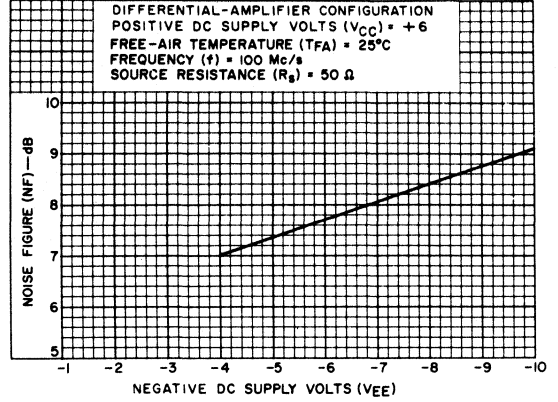


Fig. 12

COMMON-MODE-REJECTION RATIO

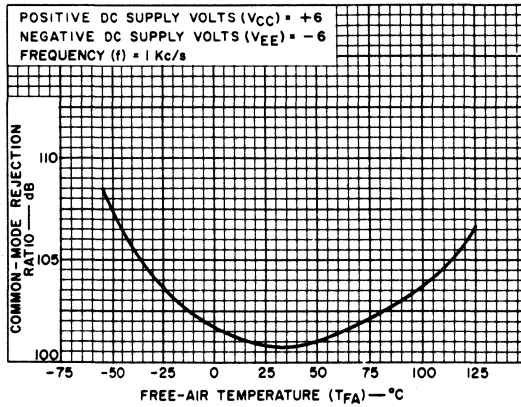


Fig. 13

TYPICAL DYNAMIC TEST CIRCUITS FOR TYPES CA3005 AND CA3006

COMMON-MODE REJECTION RATIO TEST CIRCUIT

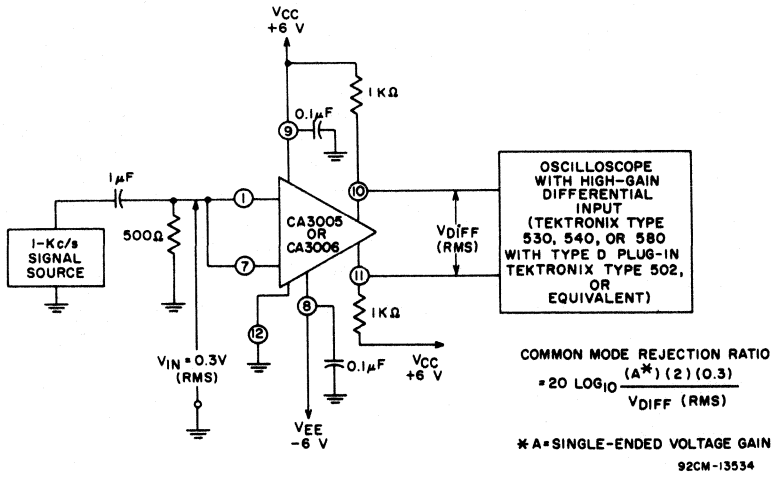


Fig. 14

AGC RANGE TEST CIRCUIT

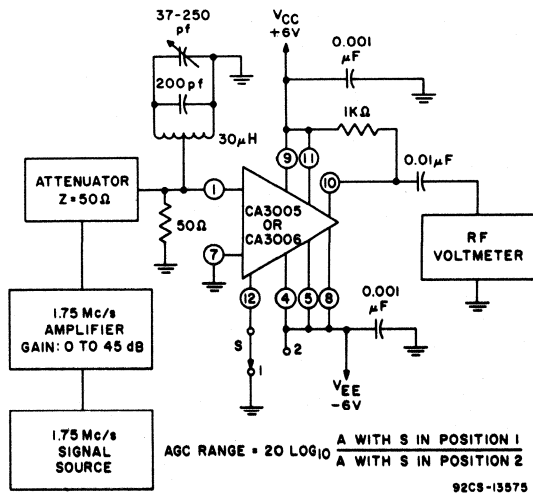
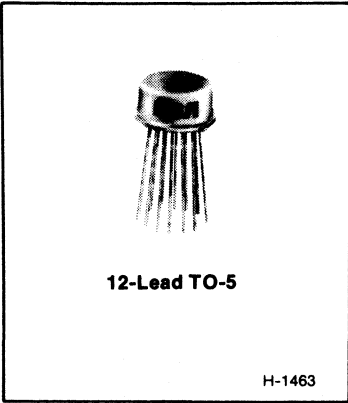


Fig. 15

CA3007



AF Amplifier

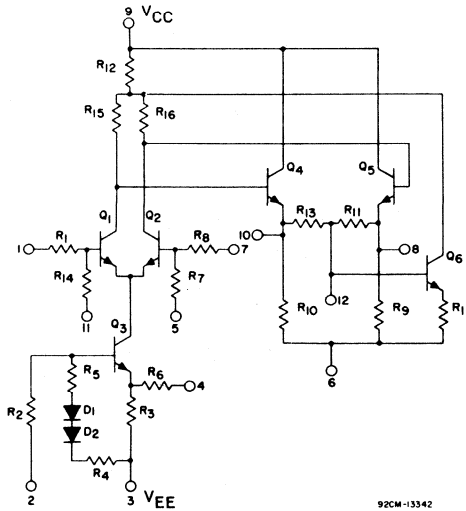
Features:

- Input impedance - 4 k Ω typ.
- Output impedance - 60 Ω typ.
- Power gain - 22 dB typ.
- Push-pull input & output
- Direct coupling to class B audio output stage
- Designed for use in sound systems and communication equipment
- Balanced differential-amplifier configuration with controlled constant-current source provides for both audio amplification and phase inversion
- Built-in temperature stability for operation from -55°C to +125°C

- Eliminates need for audio driver transformer
- Companion Application Note, ICAN 5037 "Application of the RCA-CA3007 Integrated Circuit Audio Driver" covers design of a dual supply audio driver in a direct-coupled audio amplifier, and a single supply audio driver in a capacitor-coupled audio amplifier

Applications

- Audio amplifier
- Audio driver



SCHEMATIC DIAGRAM

ABSOLUTE-MAXIMUM VOLTAGE LIMITS, at $T_A = 25^\circ\text{C}$

Indicated voltage limits for each terminal can be applied under the specified operating conditions for other terminals.
All voltages are with respect to ground ($-V_{CC}$, $+V_{EE}$, or common terminal of Positive and Negative DC supplies).

TERMINAL	VOLTAGE LIMITS		CONDITIONS	
	NEGATIVE	POSITIVE	TERMINAL	VOLTAGE
1	-2.5	+2.5	2	0
			3	-6
			6	0
			7	0
			9	+6
2	-8	0	11	0
			3	-8
			6	0
			7	0
			9	+6
3	-10	0	11	0
			6	0
			7	0
			9	+6
4	-8.5	0	11	0
			6	0
			7	0
			9	+6
5	-2.5	+2.5	11	0
			2	0
			3	-6
			6	0
			7	0
6	-3	0	9	+6
			11	0
			2	0
			3	-6
			7	0
7	-2.5	+2.5	9	+6
			11	0
			1	0
			2	0
			3	-6

TERMINAL	VOLTAGE LIMITS		CONDITIONS	
	NEGATIVE	POSITIVE	TERMINAL	VOLTAGE
8	-2	0	2	0
			3	-6
			6	0
			7	0
			9	+6
9	0	+10	11	0
			2	0
			3	-6
			6	0
			7	0
10	-2	0	11	0
			2	0
			3	-6
			6	0
			7	0
11	-2.5	+2.5	9	+6
			11	0
			1	0
			2	0
			3	-6
12	-2	0	6	0
			7	0
			9	+6
			11	0
			CASE	INTERNALLY CONNECTED TO TERMINAL No.3 (SUBSTRATE) DO NOT GROUND

OPERATING-TEMPERATURE RANGE -55°C to $+125^\circ\text{C}$

STORAGE-TEMPERATURE RANGE -65°C to $+150^\circ\text{C}$

LEAD TEMPERATURE (During Soldering)

At distance $1/16 \pm 1/32$ inch ($1.59 \pm 0.79\text{mm}$)

from case for 10 seconds max. $+265^\circ\text{C}$

MAXIMUM SINGLE-ENDED INPUT-

SIGNAL VOLTAGE ± 2.5 V

MAXIMUM COMMON-MODE INPUT-

SIGNAL VOLTAGE ± 2.5 V

MAXIMUM DEVICE DISSIPATION 300 mW

Linear Integrated Circuits

CA3007

ELECTRICAL CHARACTERISTICS, at $T_A = 25^\circ\text{C}$, $V_{CC} = +6\text{ V}$, $V_{EE} = -6\text{ V}$,

CHARACTERISTICS	SYMBOLS	SPECIAL TEST CONDITIONS Pin 4 Not Connected Unless Otherwise Noted	TEST CIRCUITS Fig.	LIMITS TYPE CA3007				TYPICAL CHARAC- TERISTICS CURVES
				Min.	Typ.	Max.	Units	Fig.
STATIC CHARACTERISTICS								
Input Unbalance Voltage	V_{IU}		3	-	0.57	5	mV	2
Input Unbalance Current	I_{IU}		3	-	0.57	5	μA	2
Input Bias Current	I_I		3	-	11	34	μA	4
Quiescent Operating Voltage	V_8 or V_{10}		3	-	0.87	-	V	5
Device Dissipation	P_T		3	-	30	-	mW	NONE
DYNAMIC CHARACTERISTICS								
Power Gain	G_p	$f = 1\text{ kHz}$	6	20	22	-	dB	NONE
Total Harmonic Distortion	THD	$f = 1\text{ kHz}$	6	-	0.28	-	%	NONE
Input Impedance	Z_{IN}	$f = 1\text{ kHz}$	7	-	4K	-	Ω	NONE
Common-Mode Rejection Ratio	CMR	$f = 1\text{ kHz}$	9(A) 9(B)	-	77	-	dB	8

TYPICAL STATIC CHARACTERISTICS AND TEST CIRCUIT FOR CA3007

INPUT UNBALANCE VOLTAGE AND CURRENT
vs TEMPERATURE

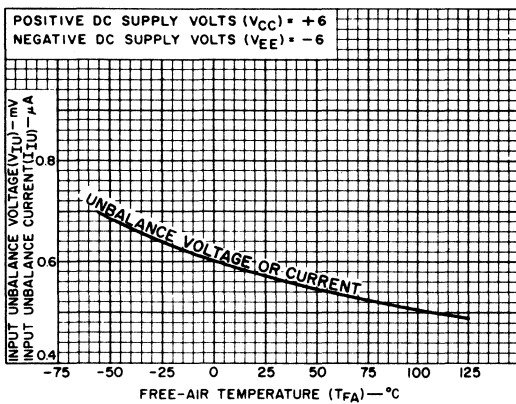
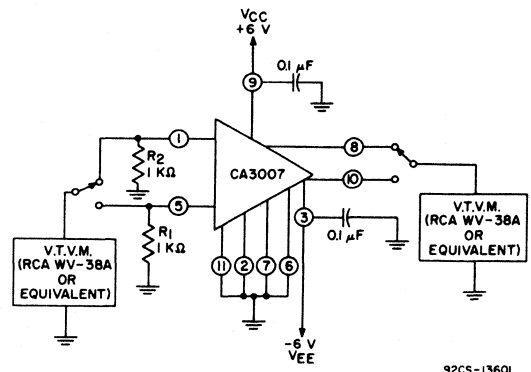


Fig. 2

INPUT UNBALANCE VOLTAGE & CURRENT, INPUT BIAS
CURRENT, QUIESCENT OPERATING VOLTAGE, AND
DEVICE DISSIPATION TEST CIRCUIT



R_1 and R_2 matched to $\pm 1\%$.

$$P_T = V_{CC}I_9 + V_{EE}I_3$$

I_9 = Direct Current into Terminal No.9

I_3 = Direct Current out of Terminal No.3

Fig. 3

INPUT BIAS CURRENT vs TEMPERATURE

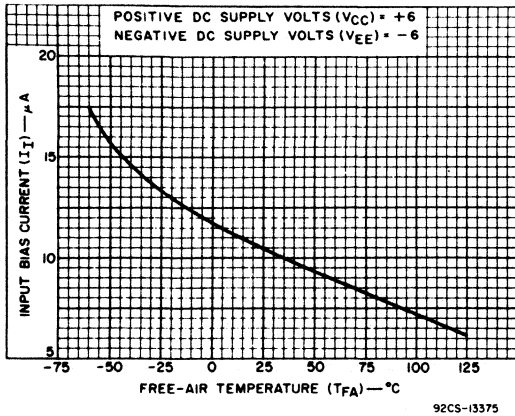


Fig. 4

QUIESCENT OPERATING VOLTAGE vs TEMPERATURE

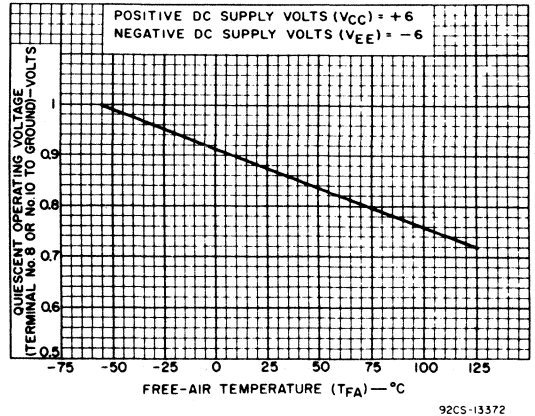
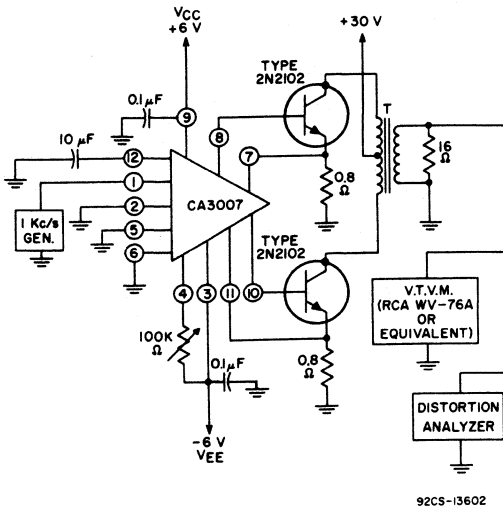


Fig. 5

TYPICAL DYNAMIC TEST CIRCUITS FOR CA3007

POWER GAIN AND TOTAL HARMONIC DISTORTION TEST CIRCUIT



T (Output Transformer):
 Primary Impedance = 2000Ω C.T.
 Secondary Impedance = 16Ω
 Efficiency = 45% approx.
 (STANCOR TYPE TA-10 OR EQUIVALENT)

Fig. 6

INPUT IMPEDANCE TEST CIRCUIT

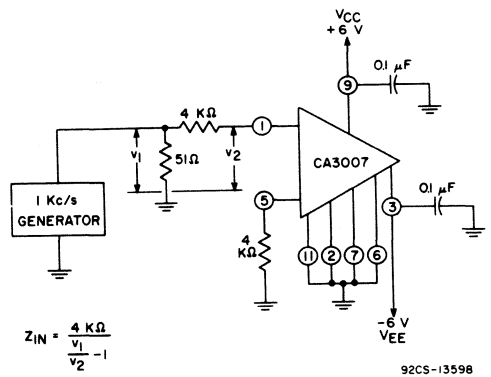


Fig. 7

TYPICAL DYNAMIC CHARACTERISTIC AND TEST CIRCUITS FOR CA3007

COMMON-MODE REJECTION RATIO vs TEMPERATURE

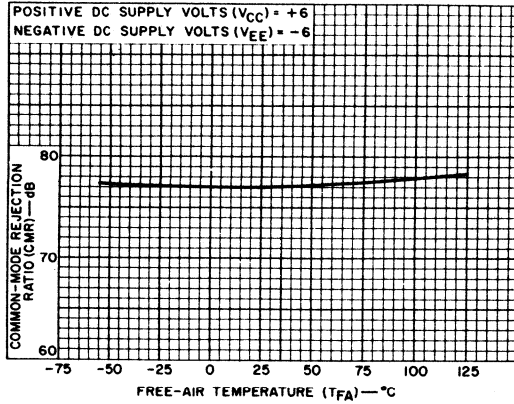
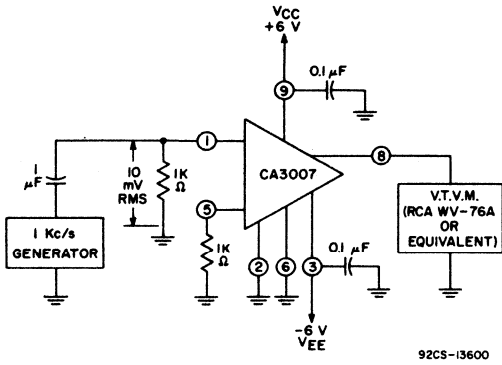


Fig. 8

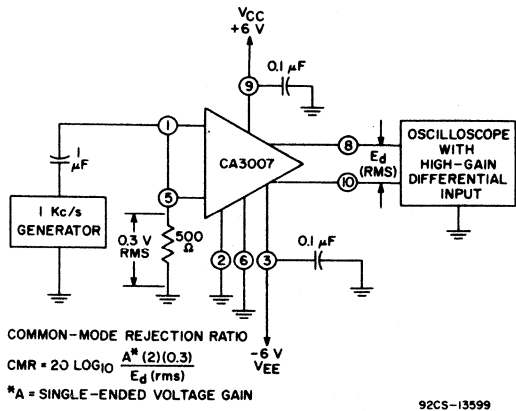
92CS-13448

COMMON-MODE REJECTION-RATIO TEST CIRCUITS



92CS-13600

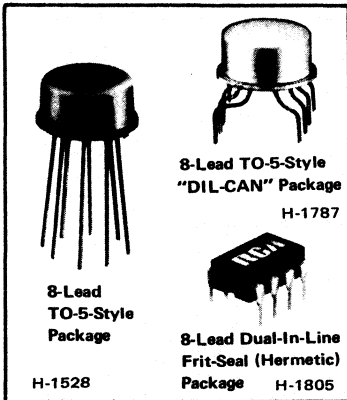
(A) Single-Ended Differential Voltage Gain



92CS-13599

Fig. 9

(B) Common-Mode Voltage Gain



DIFFERENTIAL/CASCODE AMPLIFIERS

For Communications and Industrial Equipment at Frequencies from DC to 120 MHz

FEATURES

- Controlled for Input Offset Voltage, Input Offset Current, and Input Bias Current (CA3028 Series only)
- Balanced Differential Amplifier Configuration with Controlled Constant-Current Source
- Single- and Dual-Ended Operation
- Operation from DC to 120 MHz
- Balanced-AGC Capability
- Wide Operating-Current Range

The CA3028A and CA3028B are differential/cascode amplifiers designed for use in communications and industrial equipment operating at frequencies from dc to 120 MHz.

The CA3028B is like the CA3028A but is capable of premium performance particularly in critical dc and differential amplifier applications requiring tight controls for input offset voltage, input offset current, and input bias current.

The CA3053 is similar to the CA3028A and CA3028B but is recommended for IF amplifier applications.

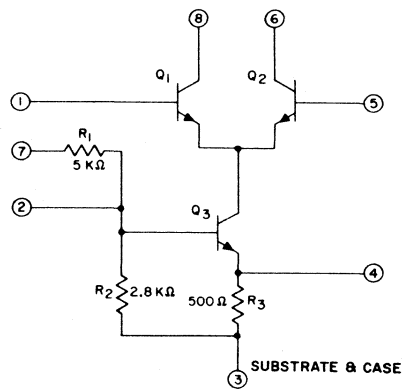
The CA3028A, CA3028B, and CA3053 are supplied in a hermetic 8-lead TO-5-style package. The "F" versions are supplied in a frit-seal TO-5 package, and the "S" versions in formed-lead (DIL-CAN) packages.

APPLICATIONS

- RF and IF Amplifiers (Differential or Cascode)
- DC, Audio, and Sense Amplifiers
- Converter in the Commercial FM Band
- Oscillator
- Mixer
- Limiter
- Companion Application Note, ICAN 5337 "Application of the RCA CA3028 Integrated Circuit Amplifier in the HF and VHF Ranges." This note covers characteristics of different operating modes, noise performance, mixer, limiter, and amplifier design considerations.

The CA3028A, CA3028B, and CA3053 are available in the packages shown below. When ordering these devices, it is important to add the appropriate suffix letter to the device.

Package 8-Lead TO-5	Suffix Letter	CA3028A	CA3028B	CA3053
TO-5	T	✓	✓	✓
With Dual-In-Line Formed Leads (DIL-CAN)	S	✓	✓	✓
Frit-Seal Ceramic	F	✓	✓	✓
Beam-Lead	L	✓		
Chip	H	✓		



92CS-14417R2

Fig.1 - Schematic diagram for CA3028A, CA3028B and CA3053.

Linear Integrated Circuits

CA3028A, CA3028B, CA3053 Types

ABSOLUTE MAXIMUM RATINGS AT $T_A = 25^\circ\text{C}$

DISSIPATION:

At T_A up to 55°C

(CA3028AF, CA3028BF,
CA3053F) 750 mW

At $T_A > 55^\circ\text{C}$

(CA3028AF, CA3028BF,
CA3053F) Derate linearly 6.67 mW/ $^\circ\text{C}$

At T_A up to 85°C

(CA3028A, CA3028B, CA3053) 450 mW

At $T_A > 85^\circ\text{C}$

(CA3028A, CA3028B, CA3053) Derate linearly 5 mW/ $^\circ\text{C}$

AMBIENT-TEMPERATURE RANGE:

Operating -55°C to $+125^\circ\text{C}$

Storage -65°C to $+150^\circ\text{C}$

LEAD TEMPERATURE (During Soldering):

At distance $1/16 \pm 1/32''$ (1.59 ± 0.79 mm)

from case for 10 seconds max. $+265^\circ\text{C}$

MAXIMUM VOLTAGE RATINGS at $T_A = 25^\circ\text{C}$

TERMINAL No.	1	2	3	4	5	6	7	8
1		0 to -15 [▲]	0 to -15 [▲]	0 to -15 [▲]	+5 to -5	*	*	+20 [Ⓢ] to 0
2			+5 to -11	+5 to -1	+15 [Ⓢ] to -1	*	+15 [Ⓢ] to 0	*
3 [†]				+10 to 0	+15 [Ⓢ] to 0	+30 [●] to 0	+15 [Ⓢ] to 0	+30 [●] to 0
4					+15 [Ⓢ] to 0	*	*	*
5						+20 [Ⓢ] to 0	*	*
6							*	*
7								*
8								

This chart gives the range of voltages which can be applied to the terminals listed horizontally with respect to the terminals listed vertically. For example, the voltage range of the horizontal terminal 4 with respect to terminal 2 is -1 to +5 volts.

[†] Terminal #3 is connected to the substrate and case.

* Voltages are not normally applied between these terminals. Voltages appearing between these terminals will be safe, if the specified voltage limits between all other terminals are not exceeded.

▲ Limit is -12V for CA3053

Ⓢ Limit is +15V for CA3053

● Limit is +24V for CA3028A and +18V for CA3053

MAXIMUM CURRENT RATINGS

TERMINAL No.	I_{IN} mA	I_{OUT} mA
1	0.6	0.1
2	4	0.1
3	0.1	23
4	20	0.1
5	0.6	0.1
6	20	0.1
7	4	0.1
8	20	0.1

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

CHARACTERISTIC	SYMBOL	TEST CIRCUIT	SPECIAL TEST CONDITIONS	LIMITS TYPE CA3028A			LIMITS TYPE CA3028B			LIMITS TYPE CA3053			UNITS	TYPICAL CHARACTERISTIC CURVES	
				Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.			
STATIC CHARACTERISTICS															
				$+V_{CC}$	$-V_{EE}$										
Input Offset Voltage	V_{IO}	2		6V 12V	6V 12V	-	-	-	0.98 0.89	5 5	-	-	-	mV	4
Input Offset Current	I_{IO}	3a		6V 12V	6V 12V	-	-	-	0.56 1.06	5 6	-	-	-	μA	4
Input Bias Current	I_T	3a		6V 12V	6V 12V	-	16.6 36	70 106	-	16.6 36	40 80	-	-	μA	5a
		3b		9V 12V	-	-	-	-	-	-	-	29 36	85 125	-	5b
Quiescent Operating Current	I_6 or I_8	3a		6V 12V	6V 12V	0.8 2	1.25 3.3	2 5	1 2.5	1.25 3.3	1.5 4	-	-	mA	6a 7
		3b		9V 12V	-	-	-	-	-	-	-	1.2 2.0	2.2 3.3	3.5 5.0	6b
AGC Bias Current (Into Constant-Current Source Terminal No.7)	I_7	8a		12V 12V	$V_{AGC} = +9$ $V_{AGC} = +12$	-	1.28	-	-	1.28	-	-	-	mA	8b
		-		9V 12V	-	-	-	-	-	-	-	1.15 1.55	-	-	-
Input Current (Terminal No.7)	I_7	-		6V 12V	6V 12V	0.5 1	0.85 1.65	1 2.1	0.5 1	0.85 1.65	1 2.1	-	-	mA	-
Device Dissipation	P_T	3a		6V 12V	6V 12V	24 120	36 175	54 260	24 120	36 175	42 220	-	-	mW	9
		3b		9V 12V	-	-	-	-	-	-	-	-	50 100	80 150	-

Differential Amplifiers

CA3028A, CA3028B, CA3053 Types

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$ (cont'd)

CHARACTERISTIC	SYMBOL	TEST CIRCUIT Fig.	SPECIAL TEST CONDITIONS	LIMITS TYPE CA3028A			LIMITS TYPE CA3028B			LIMITS TYPE CA3053			UNITS	TYPICAL CHARACTERISTICS CURVE Fig.	
				Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.			
DYNAMIC CHARACTERISTICS															
Power Gain	G _P	10a	f = 100 MHz	Cascode	16	20	-	16	20	-	-	-	-	dB	10b
		11a,d	V _{CC} = +9V	Diff.-Ampl.	14	17	-	14	17	-	-	-	-	dB	11b,e
		10a	f = 10.7 MHz	Cascode	35	39	-	35	39	-	35	39	-	dB	10b*
Noise Figure	NF	10a	f = 100 MHz	Cascode	-	7.2	9	-	7.2	9	-	-	-	dB	10c
		11a,d	V _{CC} = +9V	Diff.-Ampl.	-	6.7	9	-	6.7	9	-	-	-	dB	11c,e
Input Admittance	Y ₁₁	-	-	Cascode	-	-	-	-	0.6 + j 1.6	-	-	-	mmho	12	
Reverse Transfer Admittance	Y ₁₂	-	-	Diff.-Ampl.	-	-	-	-	0.5 + j 0.5	-	-	-	mmho	13	
		-	f = 10.7 MHz	Cascode	-	-	-	-	0.0003 - j0	-	-	-	mmho	14	
Forward Transfer Admittance	Y ₂₁	-	V _{CC} = +9V	Diff.-Ampl.	-	-	-	-	0.01 - j0.0002	-	-	-	mmho	15	
		-	-	Cascode	-	-	-	-	99 - j18	-	-	-	mmho	16	
Output Admittance	Y ₂₂	-	-	Diff.-Ampl.	-	-	-	-	-37 + j0.5	-	-	-	mmho	17	
		-	-	Cascode	-	-	-	-	0. + j0.08	-	-	-	mmho	18	
Power Output (Untuned)	P _O	20a	f = 10.7 MHz	Diff.-Ampl. 50 Ω Input-Output	-	5.7	-	-	5.7	-	-	-	μW	20b	
		21a	V _{CC} = +9V	Diff.-Ampl.	-	62	-	-	62	-	-	-	dB	21b	
AGC Range (Max. Power Gain to Full Cutoff)	AGC	21a	V _{CC} = +9V	Diff.-Ampl.	-	62	-	-	62	-	-	-	dB	21b	
		22a	f = 10.7 MHz	Cascode	-	40	-	-	40	-	-	40	-	dB	22b
		22c	V _{CC} = +0V R _L = 1 kΩ	Diff. Ampl.	-	30	-	-	30	-	-	30	-	dB	22d
Voltage Gain	A	23	V _{CC} = +6V, R _L = 2 kΩ V _{CC} = +12V, R _L = 1.6 kΩ	V _{EE} = -6V,	-	-	-	35	38	42	-	-	-	dB	-
				V _{EE} = -12V,	-	-	-	40	42.5	45	-	-	-	-	dB
Max. Peak-to-Peak Output Voltage at f = 1 kHz	V _{O(P-P)}	23	V _{CC} = +6V, R _L = 2 kΩ V _{CC} = +12V, R _L = 1.6 kΩ	V _{EE} = -6V,	-	-	-	7	11.5	-	-	-	-	V _{P-P}	-
				V _{EE} = -12V	-	-	-	15	23	-	-	-	-	-	V _{P-P}
Bandwidth at -3 dB point	BW	23	V _{CC} = +6V, R _L = 2 kΩ V _{CC} = +12V, R _L = 1.6 kΩ	V _{EE} = -6V,	-	-	-	-	7.3	-	-	-	-	MHz	-
				V _{EE} = -12V,	-	-	-	-	-	8	-	-	-	-	MHz
Common-Mode Input-Voltage Range	V _{CMR}	24	V _{CC} = +6V, V _{CC} = +12V	V _{EE} = -6V	-	-	-	-2.5	(-3.2 - 4.5)	4	-	-	-	V	-
				V _{EE} = -12V	-	-	-	-5	(-7 - 9)	7	-	-	-	-	V
Common-Mode Rejection Ratio	CMR	24	V _{CC} = +6V, V _{CC} = +12V	V _{EE} = -6V	-	-	-	60	110	-	-	-	-	dB	-
				V _{EE} = -12V	-	-	-	60	90	-	-	-	-	-	dB
Input Impedance at f = 1 kHz	Z _{IN}	-	V _{CC} = +6V, V _{CC} = +12V	V _{EE} = -6V	-	-	-	5.5	-	-	-	-	-	kΩ	-
				V _{EE} = -12V	-	-	-	-	3	-	-	-	-	-	kΩ
Peak-to-Peak Output Current	I _{P-P}	-	V _{CC} = +9V V _{CC} = +12V	f = 10.7 MHz	2	4	7	2.5	4	6	2	4	7	mA	-
				e _{in} = 400 mV Diff.-Ampl.	3.5	6	10	4.5	6	8	3.5	6	10	mA	-

* Does not apply to CA3053

Linear Integrated Circuits

CA3028A, CA3028B, CA3053 Types

DEFINITIONS OF TERMS

AGC Bias Current

The current drawn by the device from the AGC-voltage source, at maximum AGC voltage.

AGC Range

The total change in voltage gain (from maximum gain to complete cutoff) which may be achieved by application of the specified range of dc voltage to the AGC input terminal of the device.

Common-Mode Rejection Ratio

The ratio of the full differential voltage gain to the common-mode voltage gain.

Device Dissipation

The total power drain of the device with no signal applied and no external load current.

Input Bias Current

The average value (one-half the sum) of the currents at the two input terminals when the quiescent operating voltages at the two output terminals are equal.

Input Offset Current

The difference in the currents at the two input terminals when the quiescent operating voltages at the two output terminals are equal.

Input Offset Voltage

The difference in the dc voltages which must be applied to the input terminals to obtain equal quiescent operating voltages (zero output offset voltage) at the output terminals.

Noise Figure

The ratio of the total noise power of the device and a resistive signal source to the noise power of the signal source alone, the signal source representing a generator of zero impedance in series with the source resistance.

Power Gain

The ratio of the signal power developed at the output of the device to the signal power applied to the input, expressed in dB.

Quiescent Operating Current

The average (dc) value of the current in either output terminal.

Voltage Gain

The ratio of the change in output voltage at either output terminal with respect to ground, to a change in input voltage at either input terminal with respect to ground, with the other input terminal at ac ground.

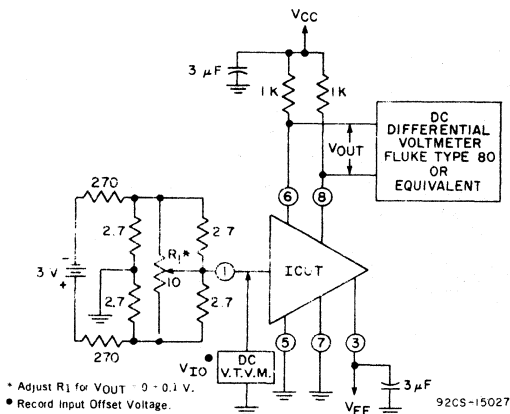


Fig.2 - Input offset voltage test circuit for CA3028B.

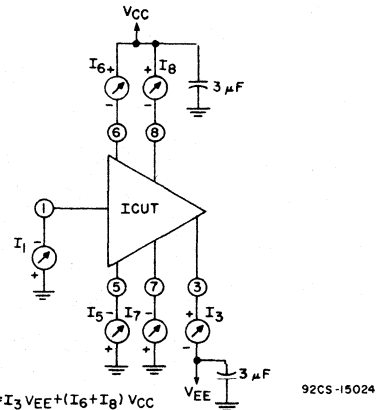


Fig.3a - Input offset current, input bias current, device dissipation, and quiescent operating current test circuit for CA3028A and CA3028B.

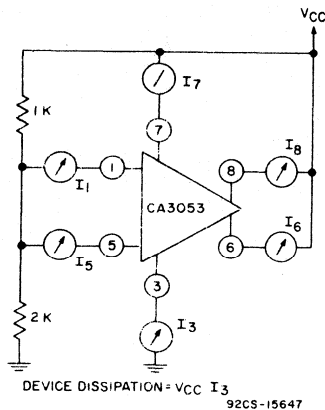


Fig.3b - Input bias current, device dissipation, and quiescent operating current test circuit for CA3053.

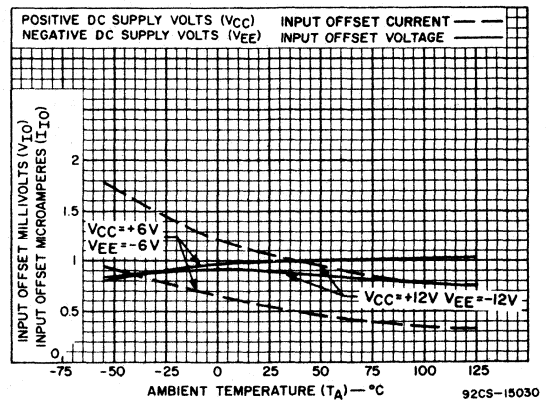


Fig.4 - Input offset voltage and input offset current for CA3028B.

CA3028A, CA3028B, CA3053 Types

TYPICAL CHARACTERISTICS

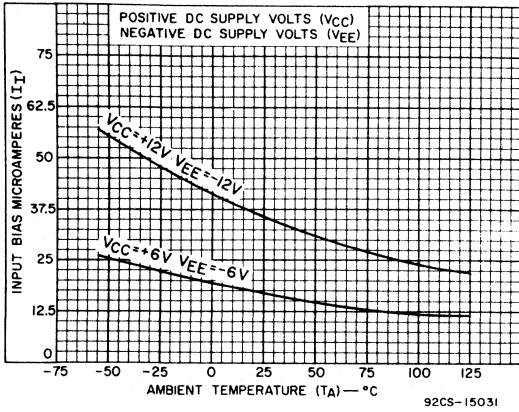


Fig.5a - Input bias current vs. ambient temperature for CA3028A and CA3028B.

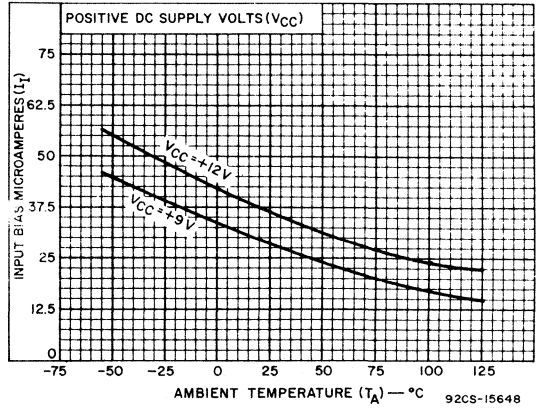


Fig.5b - Input bias current vs. ambient temperature for CA3053.

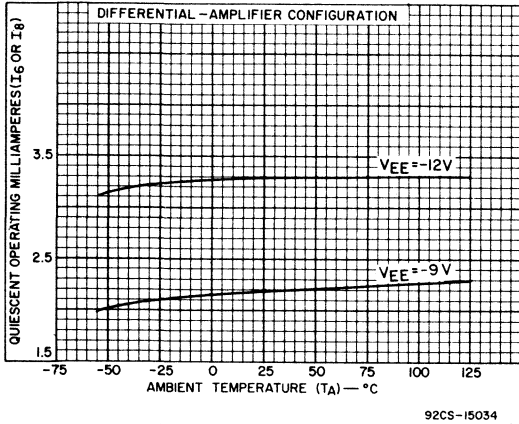


Fig.6a - Quiescent operating current vs. ambient temperature for CA3028A and CA3028B.

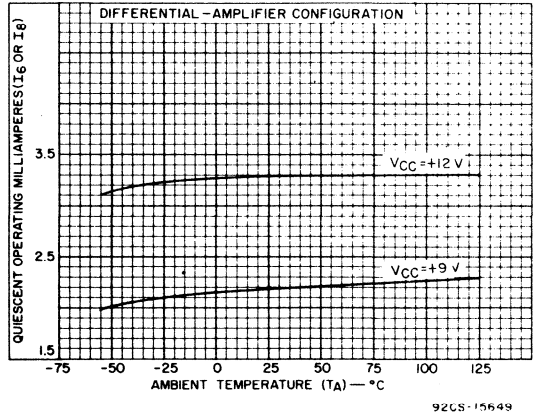


Fig.6b - Quiescent operating current vs. ambient temperature for CA3053.

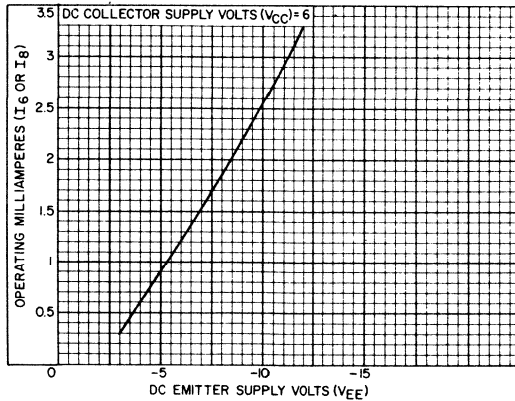
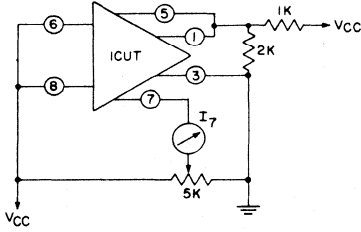


Fig.7 - Operating current vs. V_{EE} voltage for CA3028A and CA3028B.

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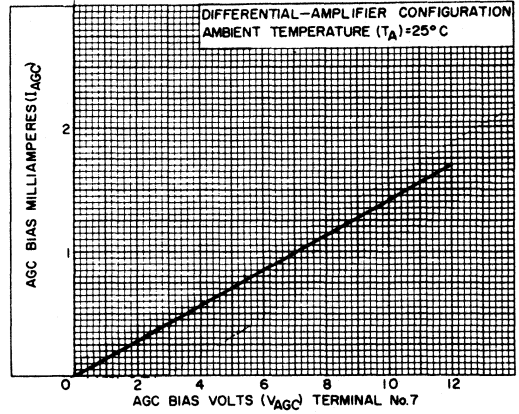
CA3028A, CA3028B, CA3053 Types

TYPICAL CHARACTERISTICS AND TEST CIRCUITS



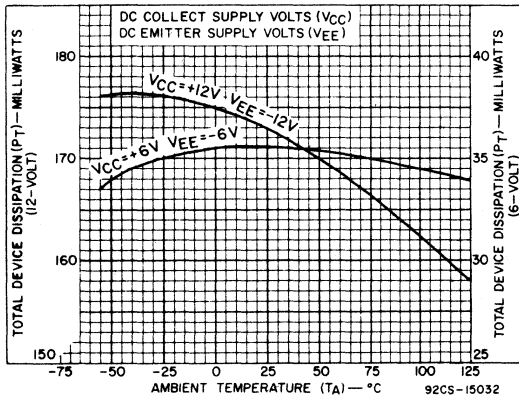
92CS-14499

Fig. 8a - AGC bias current test circuit (differential-amplifier configuration) for CA3028A and CA3028B.



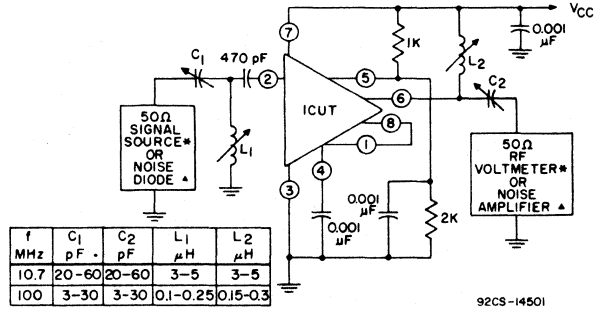
92CS-14487

Fig. 8b - AGC bias current vs. bias volts (terminal No. 7) for CA3028A and CA3028B.



92CS-15032

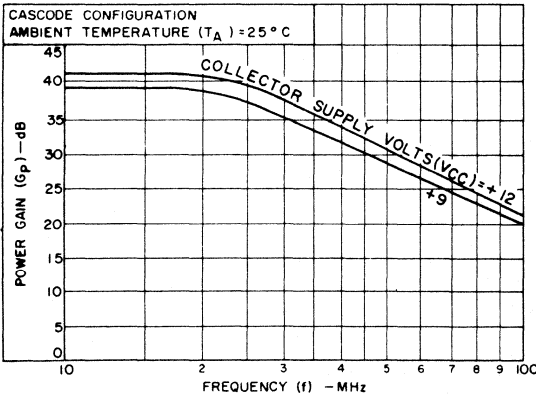
Fig. 9 - Device dissipation vs. temperature for CA3028A and CA3028B.



92CS-14501

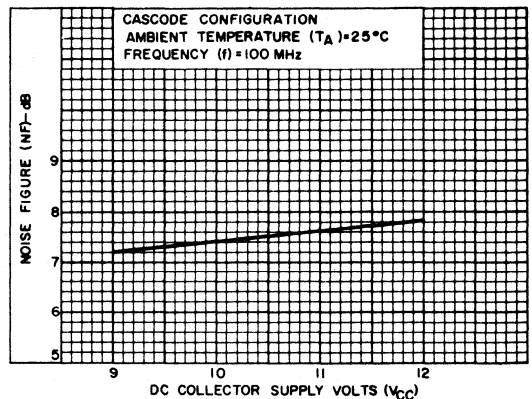
Fig. 10a - Power gain and noise figure test circuit (cascode configuration) for CA3028A, CA3028B and CA3053*.

* 10.7 MHz Power Gain Test Only.



92CS-14492

Fig. 10b - Power gain vs. frequency (cascode configuration) for CA3028A and CA3028B.



92CS-14486

Fig. 10c - 100 MHz noise figure vs. collector supply volts (cascode configuration) for CA3028A and CA3028B.

Differential Amplifiers CA3028A, CA3028B, CA3053 Types

TYPICAL NOISE FIGURE AND POWER GAIN TEST CIRCUITS AND CHARACTERISTICS

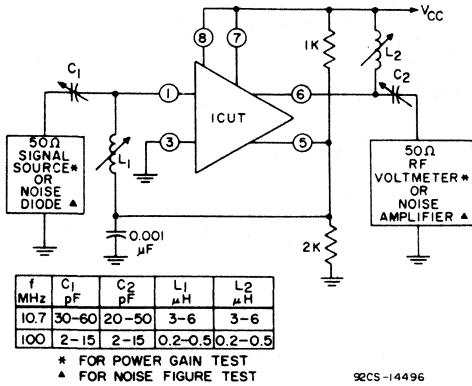
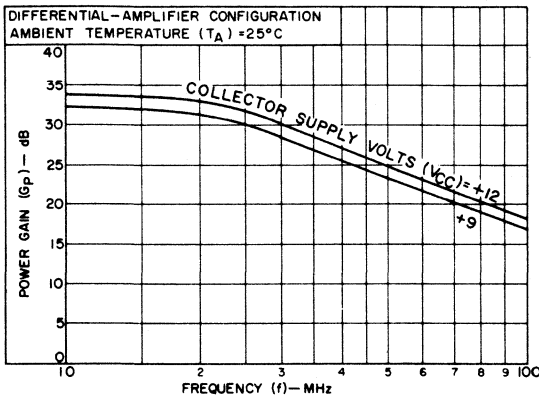


Fig. 11a - Power gain and noise figure test circuit (differential-amplifier configuration and terminal No.7 connected to V_{CC}) for CA3028A, CA3028B and CA3053*.

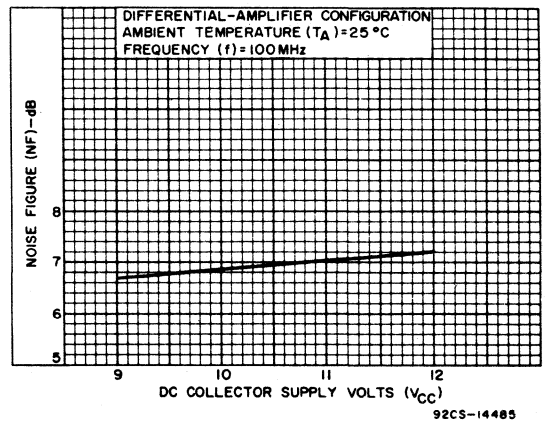
* 10.7 MHz Power Gain Test Only.

92CS-14496



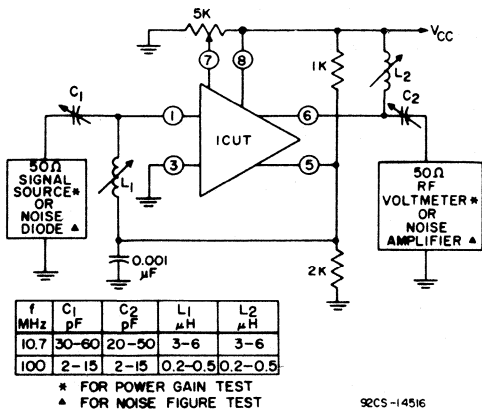
92CS-14495

Fig. 11b - Power gain vs. frequency (differential-amplifier configuration) for CA3028A and CA3028B.



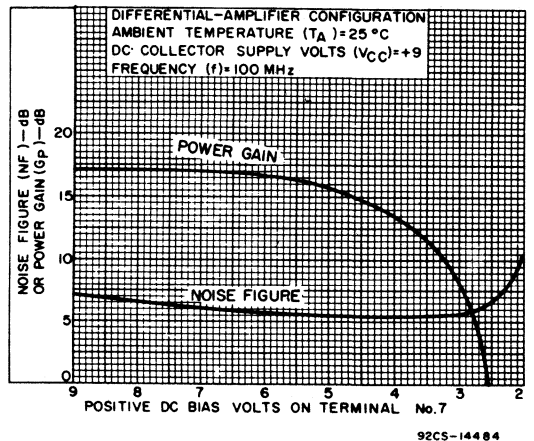
92CS-14485

Fig. 11c - 100 MHz noise figure vs. collector supply voltage (differential-amplifier configuration) for CA3028A and CA3028B.



92CS-14516

Fig. 11d - Power gain and noise figure test circuit (differential-amplifier configuration for CA3028A and CA3028B).



92CS-14484

Fig. 11e - 100 MHz noise figure and power gain vs. base-to-emitter bias (terminal No.7) for CA3028A and CA3028B.

Linear Integrated Circuits

CA3028A, CA3028B, CA3053 Types

TYPICAL ADMITTANCE PARAMETERS

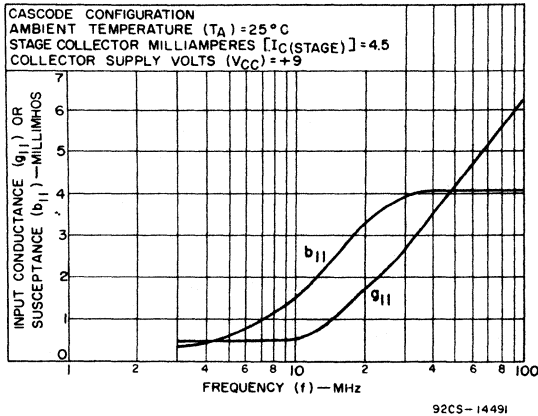


Fig.12 - Input admittance (Y_{11}) vs. frequency (cascode configuration) for CA3028A, CA3028B and CA3053.

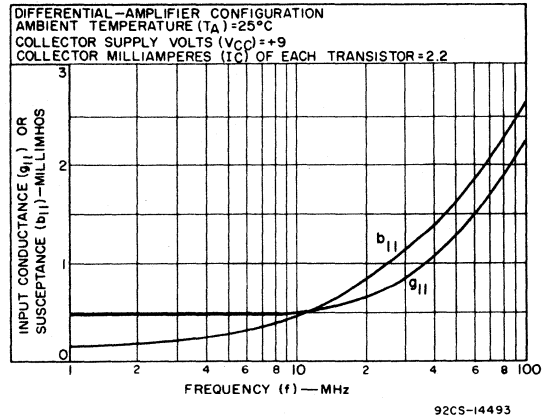


Fig.13 - Input admittance (Y_{11}) vs. frequency (differential-amplifier configuration) for CA3028A, CA3028B and CA3053.

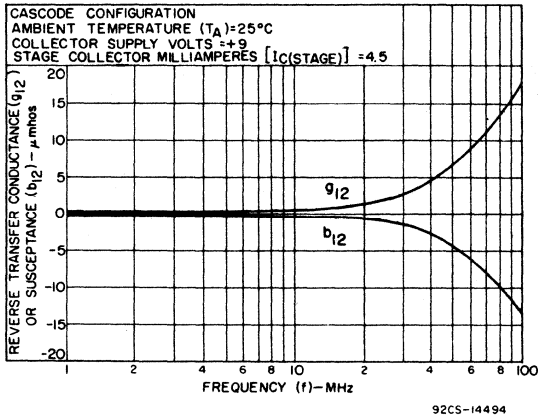


Fig.14 - Reverse transadmittance (Y_{12}) vs. frequency (cascode configuration) for CA3028A, CA3028B and CA3053.

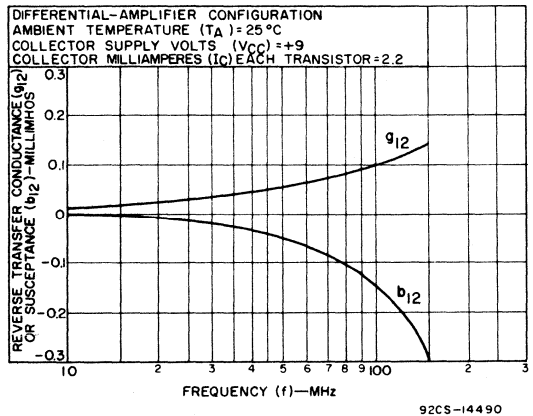


Fig.15 - Reverse transadmittance (Y_{12}) vs. frequency (differential-amplifier configuration) for CA3028A, CA3028B and CA3053.

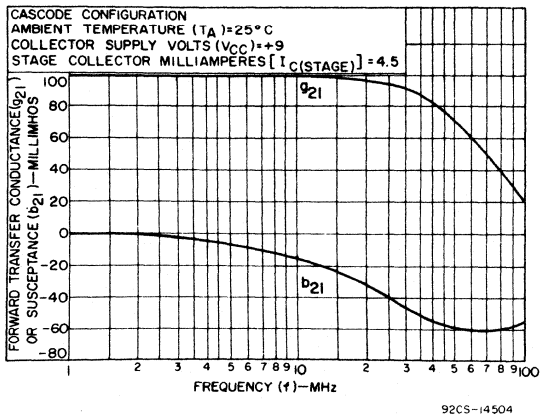


Fig.16 - Forward transadmittance (Y_{21}) vs. frequency (cascode configuration) for CA3028A, CA3028B and CA3053.

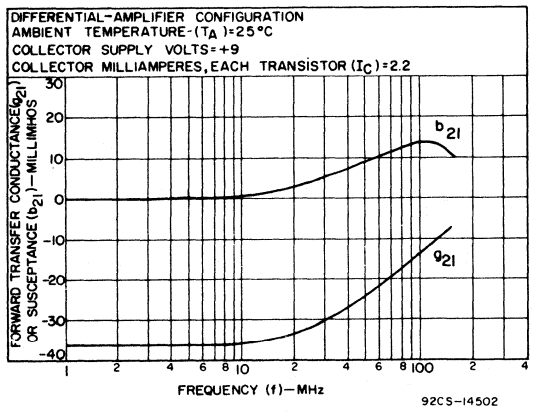
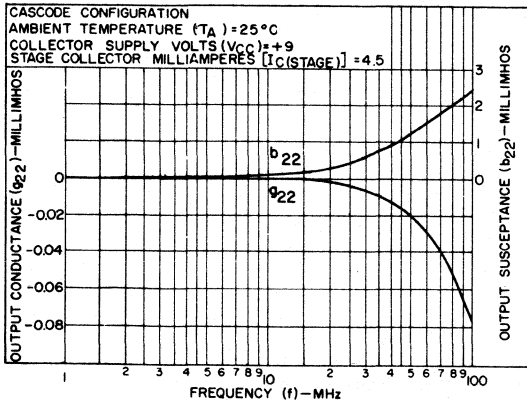


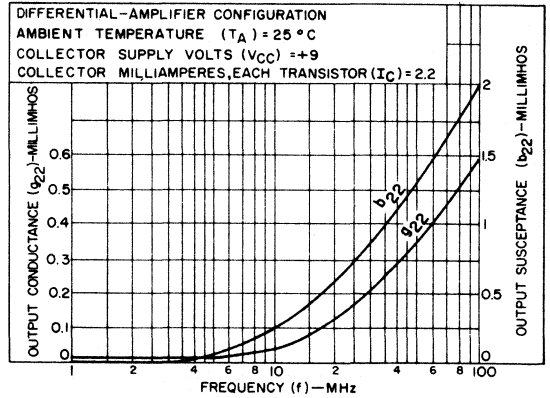
Fig.17 - Forward transadmittance (Y_{21}) vs. frequency (differential-amplifier configuration) for CA3028A, CA3028B and CA3053.

TYPICAL ADMITTANCE PARAMETERS



92CS-14505

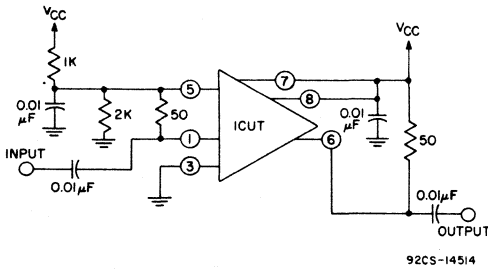
Fig.18 - Output admittance (Y_{22}) vs. frequency (cascode configuration) for CA3028A, CA3028B and CA3053.



92CS-14503

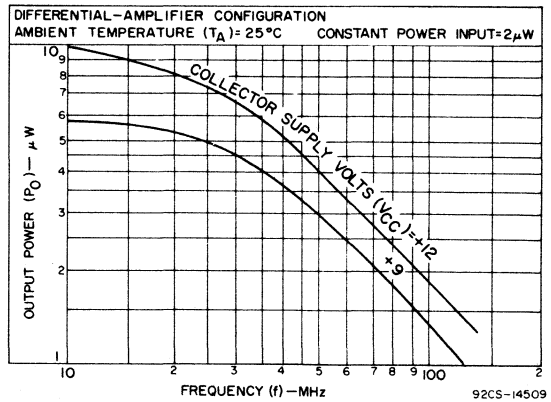
Fig.19 - Output admittance (Y_{22}) vs. frequency (differential-amplifier configuration) for CA3028A, CA3028B and CA3053.

TYPICAL TEST CIRCUITS AND CHARACTERISTICS



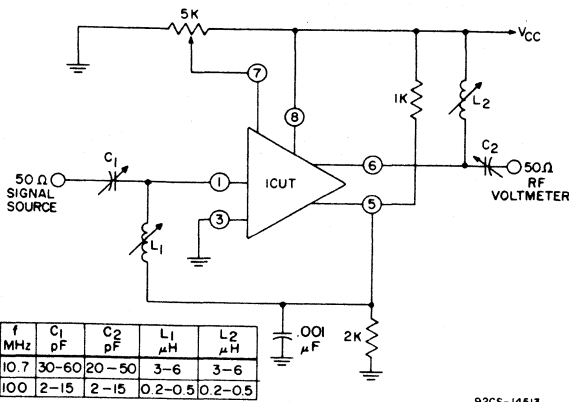
92CS-14514

Fig.20a - Output power test circuit for CA3028A and CA3028B.



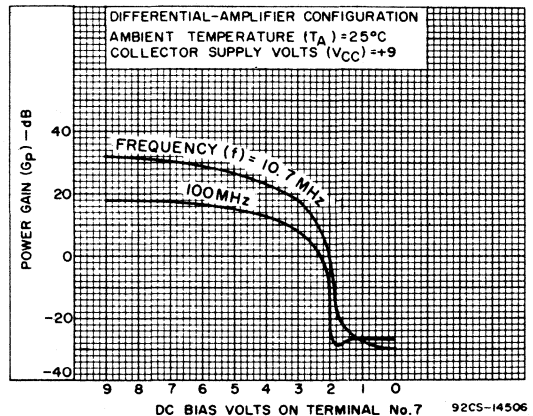
92CS-14509

Fig.20b - Output power vs. frequency - 50Ω input and 50Ω output (differential-amplifier configuration) for CA3028A and CA3028B.



92CS-14513

Fig.21a - AGC range test circuit (differential amplifier) for CA3028A and CA3028B.



92CS-14506

Fig.21b - AGC characteristics for CA3028A and CA3028B.

Linear Integrated Circuits

CA3028A, CA3028B, CA3053 Types

TEST CIRCUITS AND TYPICAL CHARACTERISTICS

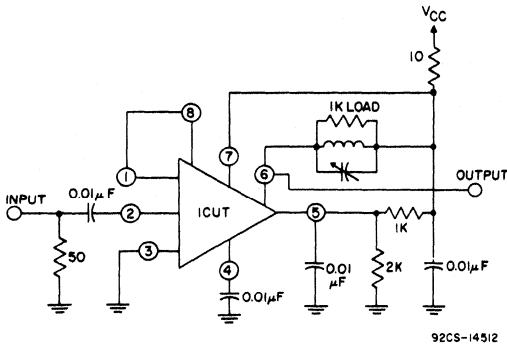


Fig.22a - Transfer characteristic (voltage gain) test circuit (10.7 MHz) cascode configuration for CA3028A, CA3028B and CA3053.

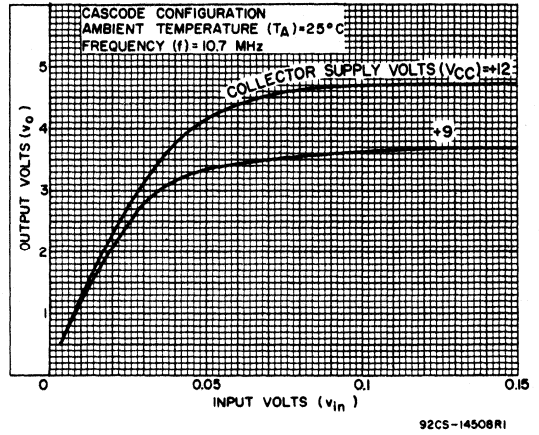


Fig.22b - Transfer characteristics (cascode configuration) for CA3028A, CA3028B and CA3053.

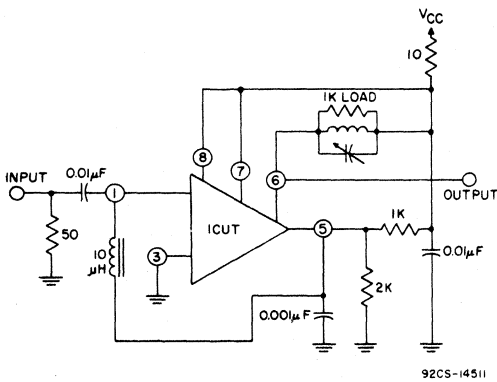


Fig.22c - Transfer characteristic (voltage gain) test circuit (10.7 MHz) differential-amplifier configuration for CA3028A, CA3028B and CA3053.

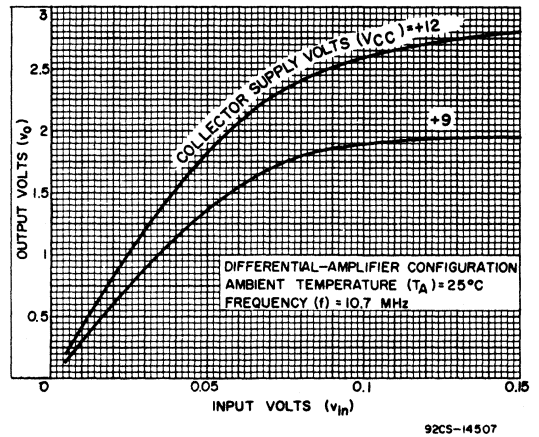
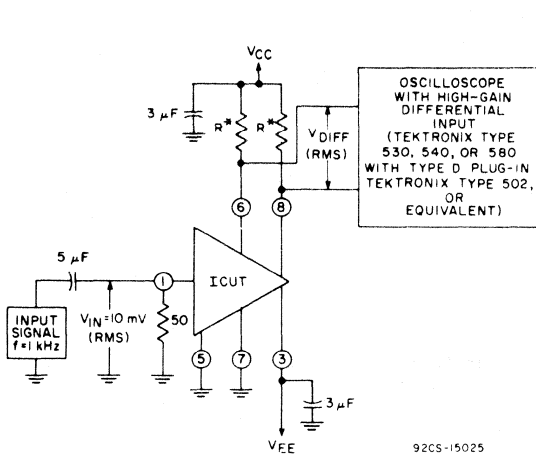


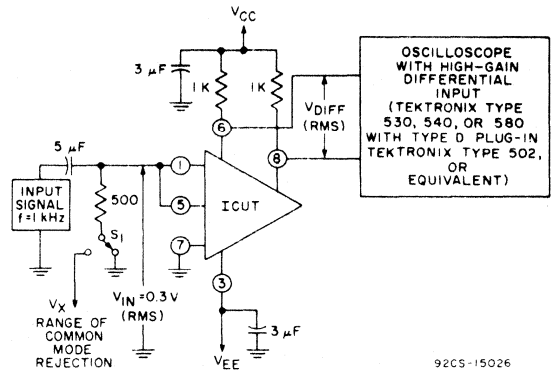
Fig.22d - Transfer characteristics (differential-amplifier configuration) for CA3028A, CA3028B and CA3053.

Differential Amplifiers CA3028A, CA3028B, CA3053 Types



* For $R = 1.6 \text{ k}\Omega$ - ($V_{CC} = 12\text{V}$, $V_{EE} = -12\text{V}$)
 For $R = 2 \text{ k}\Omega$ - ($V_{CC} = 6\text{V}$, $V_{EE} = -6\text{V}$)

Fig.23 - Differential voltage gain, maximum peak-to-peak output voltage, and bandwidth test circuit for CA3028B.



For CMR test: S_1 to ground

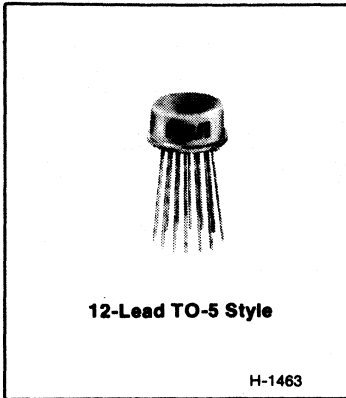
For input common-mode voltage range test: S_1 to V_X

$$\text{Common mode rejection ratio} = 20 \log_{10} \frac{(A^*) (2) (0.3)}{V_{\text{DIFF}} (\text{RMS})}$$

* A = Single-ended voltage gain.

Fig.24 - Common-mode rejection ratio and common-mode input-voltage range test circuit for CA3028B.

CA3040



Video and Wide-band Amplifier

For Industrial and Commercial Equipment at Frequencies up to 200 MHz

Features:

- High differential push-pull voltage gain - 37 dB typ.
- Single-ended voltage gain - 31 dB typ.
- Wide [3dB] bandwidth - 55 MHz typ.
- Balanced input and output
- High input resistance - 150 kΩ typ.
- Low output resistance - 125 Ω typ.
- Bias options for temperature

compensation:

- Bias Mode A: "Constant" Voltage
- Bias Mode B: "Constant" Gain

Applications

- Video amplifier
- Schmitt trigger
- Modulator
- IF Amplifier
- Mixer
- DC Amplifier
- Sense Amplifier

The RCA CA3040 is a monolithic silicon integrated circuit designed to meet the requirements of a wide variety of applications requiring high gain and wide bandwidth. The cascode-connected differential amplifier achieves a double-ended gain of 37 dB with a typical 3 dB bandwidth of 55 MHz. Emitter-Follower input and output stages provide the desirable high input impedance and output impedance for coupling to other circuits.

The CA3040 includes two biasing options, allowing the user to optimize his design over the entire military temperature

range of -55 to +125°C. **Bias Mode A** yields a substantially constant voltage at the output terminals for applications using DC coupling to succeeding stages or requiring maximum dynamic range over the temperature range. DC output voltage varies less than 0.1 volt (typically) over the entire temperature range while gain varies ± 2 dB. **Bias Mode B** provides extremely stable gain over the temperature range. Gain variation is 0 dB (typically) in this Bias Mode. DC variation is ± 0.8 volt.

Provisions are also made for stabilizing the operating point for either single or split power supplies.

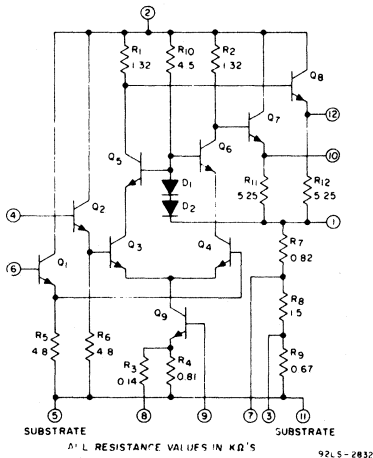


Fig. 1 — Schematic Diagram for CA3040.

The resistance values included on the schematic diagram have been supplied as a convenience to assist Equipment Manufacturers in optimizing the selection of "outboard" components of equipment designs. The values shown may vary as much as $\pm 30\%$.

RCA reserves the right to make any changes in the Resistance Values provided such changes do not adversely affect the published performance characteristics of the device.

ABSOLUTE-MAXIMUM RATINGS

DISSIPATION * 450 mW
 Derating factor for $T_A > 85^\circ\text{C}$ 5 mW/ $^\circ\text{C}$
 TEMPERATURE RANGE:
 Operating -55°C to $+125^\circ\text{C}$
 Storage -65°C to $+150^\circ\text{C}$

LEAD TEMPERATURE (During Soldering):

At distance $1/16 \pm 1/32$ inch ($1.59 \pm 0.79\text{mm}$)
 from case for 10 seconds max. $+265^\circ\text{C}$

* Limitation imposed by the thermal resistance of package.

MAXIMUM VOLTAGE RATINGS at $T_A = 25^\circ\text{C}$

The following chart gives the range of voltages which can be applied to the terminals listed vertically with respect to the terminals listed horizontally. For example, the voltage range of the vertical terminal 2 with respect to terminal 11 is 0 to +14 volts.

TERMINAL No.	1	2	3	4	5 [▲]	6	7	8	9	10	11 [▲]	12
1		0 -14	*	*	+14 0	*	+10 -10	*	*	*	+14 0	*
2			*	+14 0	+14 0	+14 0	*	*	*	+14 0	+14 0	+14 0
3				*	+5 -3	*	*	*	*	*	+5 -3	*
4					*	+3 -3	*	*	*	*	*	*
5 [▲]					▲	*	+10 -3	*	+3 -7	*	0 Note 1	*
6							*	*	*	*	*	*
7								*	*	*	+10 -3	*
8									+3 -3	*	*	*
9										*	+7 -3	*
10											*	*
11 [▲]											▲	*
12												

MAXIMUM CURRENT RATINGS

TERMINAL No.	I _{IN} mA	I _{OUT} mA
1	5	5
2	-	-
3	5	5
4	1	0.1
5	-	-
6	1	0.1
7	5	5
8	5	5
9	1	0.1
10	-	10
11	-	-
12	-	10

▲ Reference Substrate

Note 1: External connection required for proper operation.

* Voltages are not normally applied between these terminals. Voltages appearing between these terminals will be safe if the specified limits between all other terminals are not exceeded.

Linear Integrated Circuits

CA3040

ELECTRICAL CHARACTERISTICS AT $T_A = 25^\circ\text{C}$ Unless Otherwise Specified

Characteristics	Symbols	Test Circuits	Special Test Conditions	Limits			Units	Typical Characteristics Curves
				CA3040				
				Fig.	Min.	Typ.		Max.
STATIC CHARACTERISTICS $V_{CC} = +6\text{V}$, $V_{EE} = -6\text{V}$								
Output Voltage	V_{10} or V_{12}	2(a) 2(b)	Bias Mode Switch A or B: Closed	1.4	2.7	3.7	V	9
Base Bias Voltage	V_9	2(a)	Bias Mode A Switch Closed	-	-1.7	-	V	-
		2(b)	Bias Mode B Switch Closed	-	-1.7	-	V	-
Input Bias Reference Voltage	V_1	2(a) 2(b)	Bias Mode Switch A or B: Open	-1	-	+1	V	9
Input Bias Current	I_4, I_6	2(a) 2(b)	Bias Mode Switch A or B: Closed	-	15	45	μA	-
Input Unbalance Current	$ I_6 - I_4 $	2(a) 2(b)	Bias Mode Switch A or B: Closed	-	-	6	μA	-
Power Supply Current Drain	I_2 or $I_5 + I_{11}$	2(a)	Mode A Switch open or closed	4.7	8.5	15.5	mA	10
	I_2 or $I_5 + I_8 + I_{11}$	2(b)	Mode B Switch open or closed					
DYNAMIC CHARACTERISTICS $V_{CC} = +12\text{V}$, $V_{EE} = 0$; Split Voltage Supply (Optional) = +6V								
Differential Voltage Gain								-
Single-Ended Input Differential Output	$A_{\text{DIFF(DE)}}$	3(a)	$f = 1\text{ MHz}$ $R_S = 50\ \Omega$	34	37	-	dB	-
Single-Ended Input and Output	$A_{\text{DIFF(SE)}}$	3(a)	$f = 1\text{ MHz}$ $R_S = 50\ \Omega$	28	31	-	dB	4,5
-3dB Bandwidth	BW	3(a)	$R_S = 50\ \Omega$	40	55	-	MHz	4,7
Differential Voltage Gain Balance	$A_{\text{DIFF(SE)10}}$ $-A_{\text{DIFF(SE)12}}$	3(a)	$f = 1\text{ MHz}$	-1	0	+1	dB	-
Output Voltage Swing	V_8 or V_{10} RMS	3(a)	$f = 1\text{ MHz}$ $R_S = 50\ \Omega$	-	0.5	-	V _{RMS}	7
Noise Figure	NF	3(a)	(Note 1) $f = 30\text{ MHz}$ $R_S = 400\ \Omega$	-	7.5	9	dB	8
Parallel Input Resistance	R_i	3(a)	$f = 1\text{ MHz}$	-	150	-	$k\Omega$	-
Parallel Input Capacitance	C_i	3(a)		-	2.2	-	pF	-
Output Resistance	R_o	3(a)		-	125	-	Ω	-
TEMPERATURE DEPENDENT CHARACTERISTICS Temperature coefficients for ambient temperature: $-55^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$								
Output Voltage	$\frac{\Delta V_{10} \text{ or } \Delta V_{12}}{^\circ\text{C}}$	3(a)	Bias Mode A	-	0	-	mV/ $^\circ\text{C}$	9
		3(b)	Bias Mode B	-	6.4	-	mV/ $^\circ\text{C}$	
Power Supply Current Drain	$\Delta I_2 / ^\circ\text{C}$	3(a)	Bias Mode A	-	5	-	$\mu\text{A}/^\circ\text{C}$	11
Differential Voltage Gain	$A_{\text{DIFF}} / ^\circ\text{C}$	3(a)	Bias Mode A	-	0.0166	-	dB/ $^\circ\text{C}$	12
		3(b)	Bias Mode B	-	0	-	dB/ $^\circ\text{C}$	

Note 1: Replace 1-k Ω resistors between Term. 1 and 4 and Term. 1 and 6 with suitable chokes so that reactance at 30 MHz exceeds 5k Ω

STATIC CHARACTERISTICS TEST CIRCUITS FOR CA3040

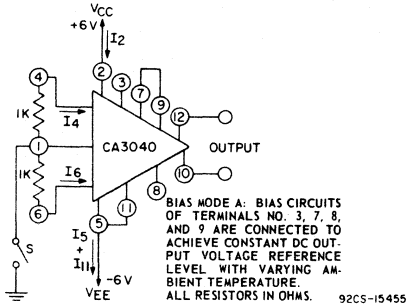


Fig.2(a) - Bias Mode A

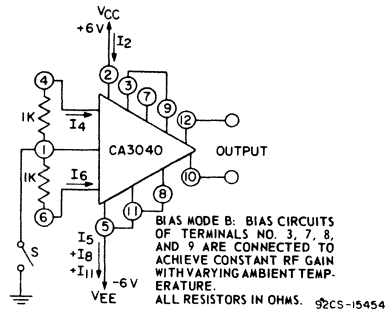
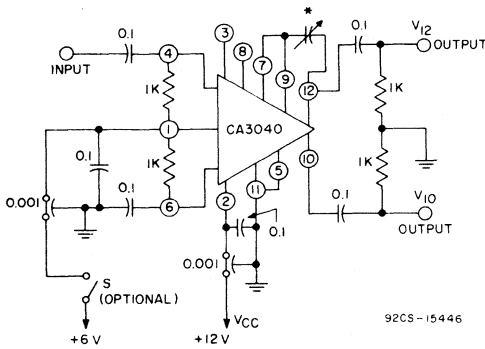


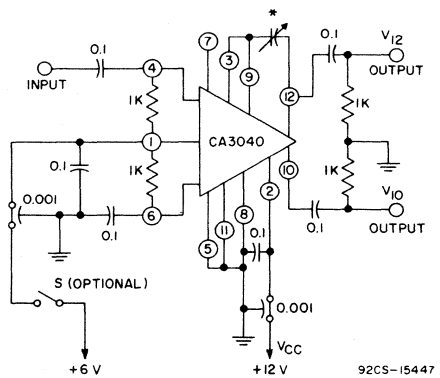
Fig.2(b) - Bias Mode B

DYNAMIC CHARACTERISTICS TEST CIRCUITS FOR CA3040



* VARIABLE CAPACITANCE (0.5-10 μ F) ADJUSTMENT FOR EQUAL 3dB BANDWIDTH AT AMPLIFIER OUTPUTS, TERMINALS 10 AND 12.
ALL RESISTORS IN OHMS.
ALL CAPACITORS IN MICROFARADS (UNLESS OTHERWISE INDICATED).
BIAS MODE A IS AS DEFINED IN FIG. 2 (a)

Fig.3(a) - Bias Mode A



* SEE FIG 3 (a)
BIAS MODE B IS AS DEFINED IN FIG 2 (b)
ALL RESISTORS IN OHMS.
ALL CAPACITORS IN MICROFARADS (UNLESS OTHERWISE INDICATED).

Fig.3(b) - Bias Mode B

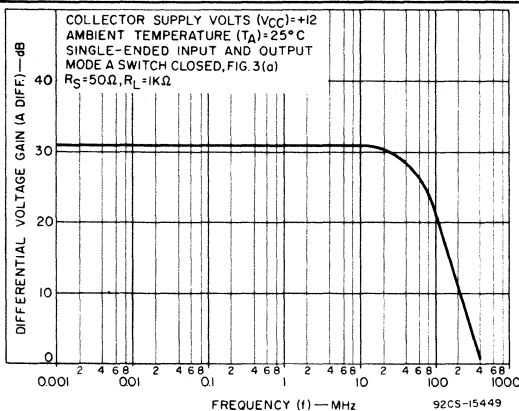


Fig.4 - Differential Voltage Gain vs Frequency

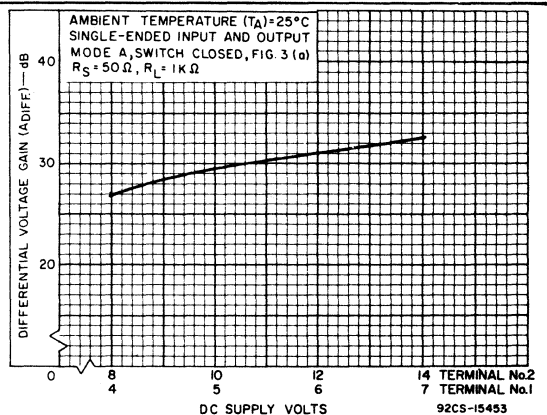


Fig.5 - Differential Voltage Gain vs DC Supply Voltages

Linear Integrated Circuits

CA3040

OPERATING CONSIDERATIONS

General

The CA3040 is designed to provide flexibility in the selection of power supply configurations and to provide the circuit designer the choice between two modes of temperature-compensated performance. Mode A, which provides constant DC output voltage, is recommended for most applications. The control of the operating point provided by this mode maintains the dynamic range of the device while gain variation over most of the range is less than ± 1 dB. Mode B provides constant gain for applications where this consideration is critical, but will exhibit a reduction of dynamic range at the temperature extremes.

Power Supply Considerations

Figures 2 and 3 illustrate the use of the CA3040 with balanced dual supplies and single power supplies, respectively. Both figures demonstrate that the inputs may be directly referenced to the center point of the supply (ground in Fig.2) by closing the included switch. This is the natural connection in Fig.2. This connection is optional, however, and need not be made. Use of this connection in Fig.3 implies the presence of another DC supply or a "stiff" bleeder. If such a source is present its use is suggested in order to maintain maximum common mode range. Dynamic performance and dynamic range of the output circuit are unaffected by the choice of biasing scheme used so that in most cases direct connection of Terminal No.1 to the center point of the supply is not required. Where direct connection is not used, Terminals No.4 and No.6 must be biased from Terminal No.1 for proper operation.

High-Frequency Considerations

Stable high-frequency operation requires that proper high-frequency construction techniques be followed. The photograph of Fig.6 illustrates the precautions taken in the construction of the test circuit of Fig.3.

Extreme caution is required because of the extended gain bandwidth capability of the device. Oscillations have been observed in the 400-to-800 MHz range when

precautions were not taken. In addition to normal considerations of shielding, parts layout, and isolation, the following specific suggestions are made:

1. Use sockets only when necessary. Sockets, when used, must provide shielding within the pin circle. The socket shown in the chassis of Fig.6 is a Barnes MG-1201, or equivalent, modified by drilling a $1/8"$ hole in the center and inserting a grounded brass pin.
2. Do not bypass Terminal No.9 in normal operation. Fig.3 shows the use of neutralization between Terminal No.9 and one output to balance the amplifier at high frequencies. Experience shows that stable operation, while possible, is difficult to achieve if Terminal No.9 is bypassed to ground.
3. In DC testing, $1\text{ k}\Omega$, $1/4\text{ W}$ carbon resistors should be soldered directly to the socket Terminals No.4 and No.6 to suppress parasitic oscillations. All current carrying connections are made at the other end of the resistors. Direct sensing of Terminal No.4 or No.6 voltage should not be attempted.

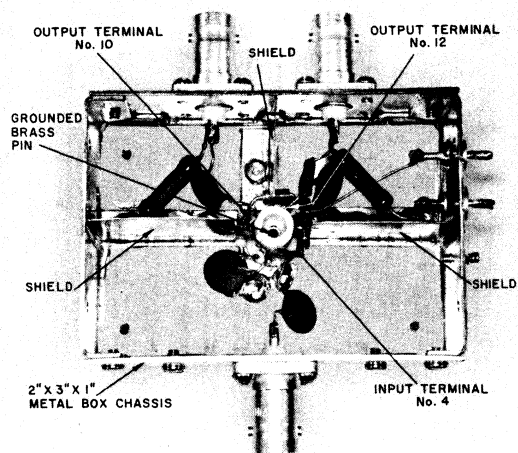
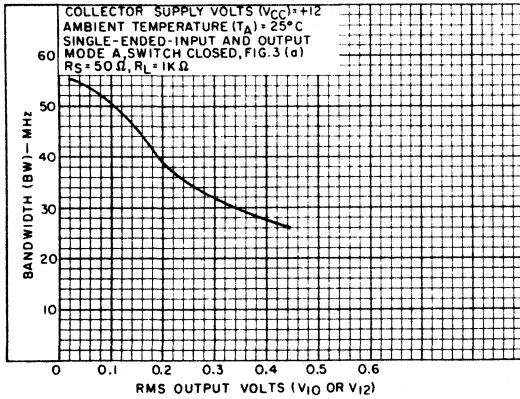
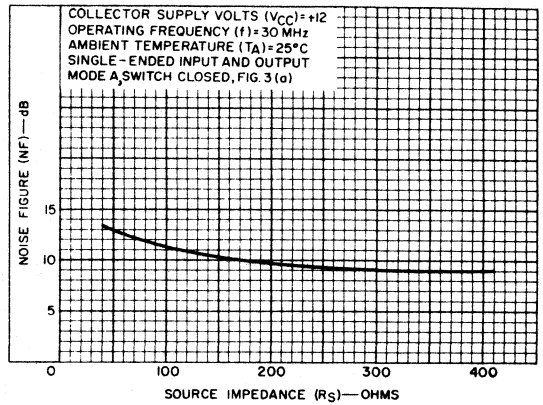


Fig.6 - Test Circuit Layout



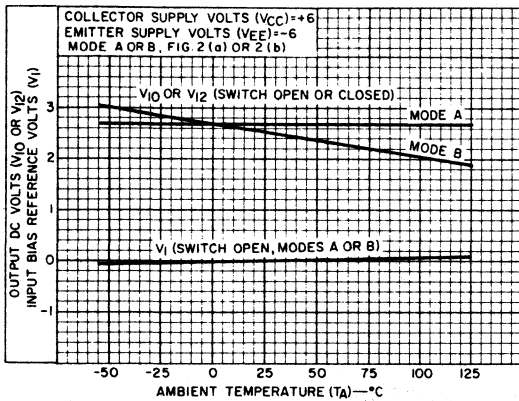
92CS-15444

Fig.7 - 3dB Bandwidth vs Single-Ended Output Voltage



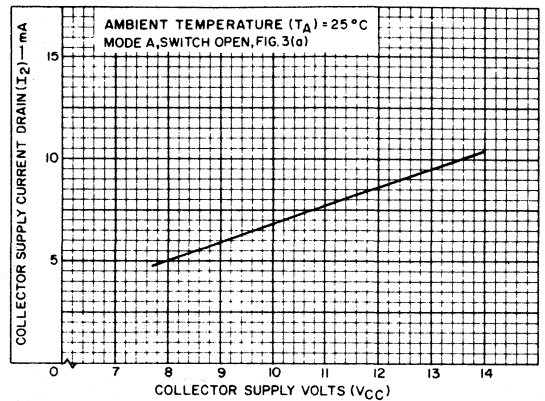
92CS-15448

Fig.8 - Noise Figure (NF) vs Source Impedance



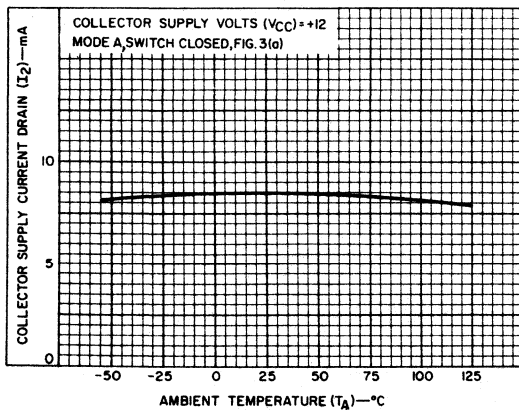
92CS-15445

Fig.9 - Output Volts or Input Bias Reference Volts vs Ambient Temperature



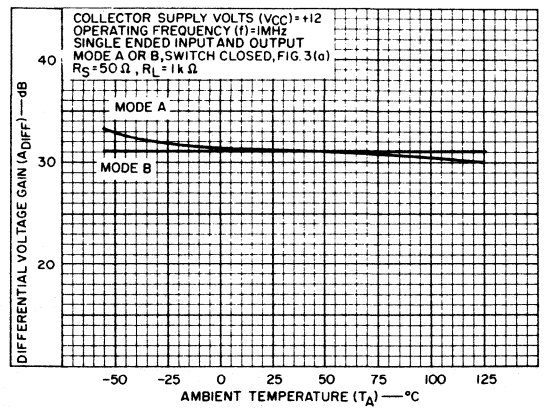
92CS-15452

Fig.10 - Collector Supply Current Drain (I_2) vs Collector Supply Voltage (V_{CC})



92CS-15451

Fig.11 - Collector Supply Current Drain (I_2) vs Ambient Temperature



92CS-15450

Fig.12 - Single-Ended Differential Voltage Gain vs Ambient Temperature

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Single-Chip Detector Alarm Systems

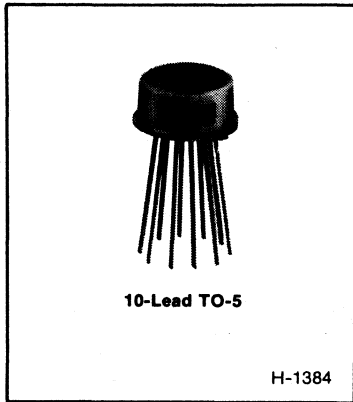
CA3164.....	647
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Timer

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*BIMOS types

CA3002



IF Amplifier

For Use in Communication Equipment

Features:

- Input resistance - 100 kΩ typ.
- Output resistance - 70 Ω typ.
- Voltage gain - 24 dB typ. @ 1.75 MHz
- Push-pull input, single-ended output
- -3 dB bandwidth - 11 MHz typ.

- AGC range - 80 dB typ.
- Useful frequency range DC to 15 MHz.

Applications:

- Product detector
- IF & video amplifier
- AM detector
- Schmitt trigger

The RCA-CA3002 integrated-circuit IF amplifier is a balanced differential amplifier that can be used with either a single-ended or a push-pull input and can provide either a direct-coupled or a capacitance-coupled single-ended output. Its applications include RC-coupled IF amplifiers that

use the internal silicon output-coupling capacitor, video amplifiers that use an external coupling capacitor, envelope detectors, product detectors, and various trigger circuits. The CA3002 is supplied in the 10-lead hermetic TO-5 style package.

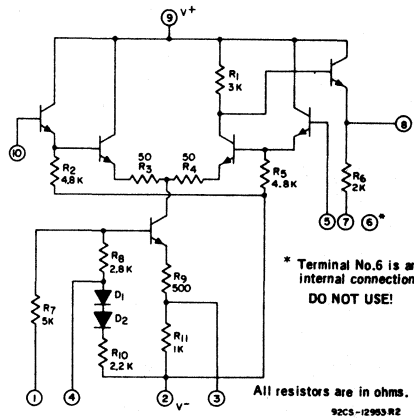


Fig. 1 — Schematic diagram.

ABSOLUTE-MAXIMUM VOLTAGE AND CURRENT LIMITS, at $T_A = 25^\circ\text{C}$

COMMON-MODE INPUT SIGNAL VOLTAGE	$\pm 2\text{ V}$
MAXIMUM POWER SUPPLY VOLTAGE	16 V or $\pm 8\text{ V}$
OPERATING-TEMPERATURE RANGE	-55°C to $+125^\circ\text{C}$
STORAGE-TEMPERATURE RANGE	-65°C to $+150^\circ\text{C}$
LEAD TEMPERATURE (During Soldering):	
At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10 seconds max.	$+265^\circ\text{C}$
MAXIMUM INPUT-SIGNAL VOLTAGE	$\pm 4\text{ V}$
MAXIMUM DEVICE DISSIPATION:	
-55 to 85°C	450 mW
Above 85°C	Derate linearly 5 mW/ $^\circ\text{C}$

ELECTRICAL CHARACTERISTICS, at $T_A = 25^\circ\text{C}$, $V_{CC} = +6\text{ V}$, $V_{EE} = -6\text{ V}$

CHARACTERISTICS	SPECIAL TEST CONDITIONS TERMINALS No. 3 & No.4 NOT CONNECTED UNLESS OTHERWISE NOTED		TEST CIRCUITS	LIMITS			U N I T S
				CA3002			
			Fig.	Min.	Typ.	Max.	
STATIC CHARACTERISTICS							
Input Unbalance Voltage V_{IU}			4	—	2.2	—	mV
Input Unbalance Current I_{IU}			5	—	2.2	10	μA
Input Bias Current I_I			5	—	20	36	μA
Quiescent Operating Voltage	MODE	TERMINAL					
		2 4					
	A	V_{EE} NC	7a	—	2.8	—	V
B	V_{EE} V_{EE}	8b	—	3.9	—	V	
Device Dissipation P_T			4	—	55	—	mW
DYNAMIC CHARACTERISTICS							
Differential Voltage Gain A_{DIF} (Single-Ended Input and Output)	$f = 1.75\text{ MHz}$		10	19	24	—	dB
Bandwidth at -3 dB Point BW	—		10	—	11	—	MHz
Maximum Output Voltage Swing $V_{OUT(P-P)}$	—		10	—	5.5	—	V_{P-P}
Noise Figure NF	$f = 1.75\text{ MHz}$ $R_S = 1\text{ k}\Omega$		12	—	4	8	dB
Input Impedance Components:							
Parallel Input Resistance R_{IN}	$f = 1.75\text{ MHz}$		None	—	100k	—	Ω
Parallel Input Capacitance C_{IN}	$f = 1.75\text{ MHz}$		None	—	4	—	pF
Output Resistance R_{OUT}	$f = 1.75\text{ MHz}$		14	—	70	—	Ω
3rd Harmonic Intermodulation Distortion IMD	—		16	-30	-40	—	dB
AGC Range (Maximum Voltage Gain to Complete Cutoff AGC)	$f = 1.75\text{ MHz}$		18	60	80	—	dB

Linear Integrated Circuits

CA3002

ABSOLUTE-MAXIMUM VOLTAGE AND CURRENT LIMITS, at $T_A = 25^\circ\text{C}$

Indicated voltage or current limits for each terminal can be applied under the specified operating conditions for other terminals.

All voltages are with respect to ground ($-V_{CC}$, $+V_{EE}$) or common terminal of Positive and Negative DC supplies).

TERMINAL	VOLTAGE OR CURRENT LIMITS		CONDITIONS	
	NEGATIVE	POSITIVE	TERMINAL	VOLTAGE
1	-8 V	0 V	2, 7 5, 10 9	-8 0 +6
2	-10 V	0 V	1, 5, 10 9	0 +6
3	-8.5 V	0 V	1, 5, 10 7 9	0 -6 +6
4	-8 V	0 V	1, 5, 10 2, 7 9	0 -8 +6
5	-3.5 V	+3.5 V	1, 10 2, 7 9	0 -6 +6
6	INTERNAL CONNECTION DO NOT USE			
7	-12 V	0 V	1, 5, 10 2 9	0 -6 +6
8	20 mA		1, 5, 10 2 9	0 -6 +6
			200 Ω Resistor Between Terminals 7 & 8	
9	0 V	+10 V	1, 5, 10 2, 3, 7	0 -6
10	-3.5 V	+3.5 V	1, 5 2, 7 9	0 -6 +6
CASE	INTERNALLY CONNECTED TO TERMINAL No.2 (SUBSTRATE) DO NOT GROUND			

STATIC CHARACTERISTICS

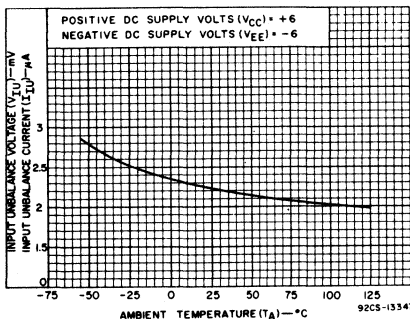


Fig. 2 - Input unbalance voltage & current vs temperature.

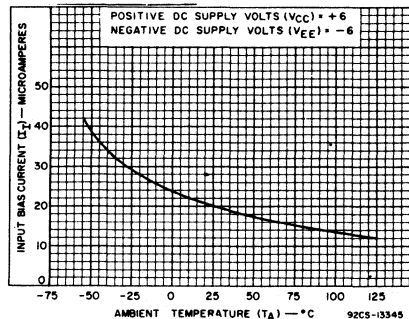


Fig. 3 - Input bias current vs temperature.

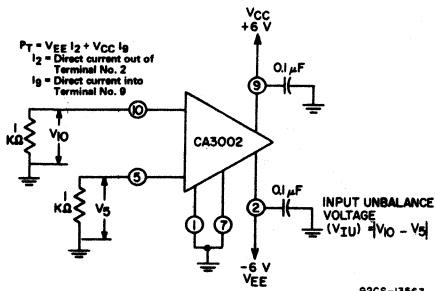


Fig. 4 – Input unbalance voltage and device dissipation test circuit.

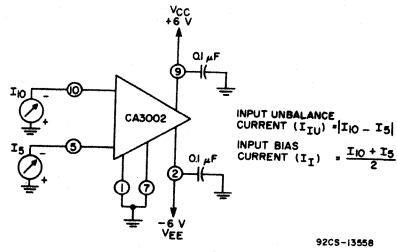


Fig. 5 – Input unbalance current & bias current test circuit.

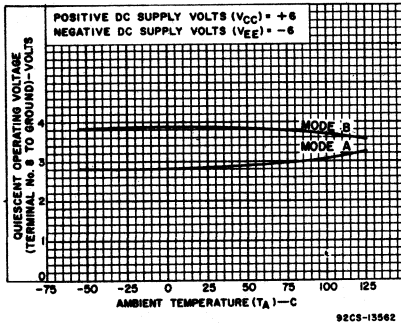


Fig. 6 – Quiescent operating voltage vs temperature.

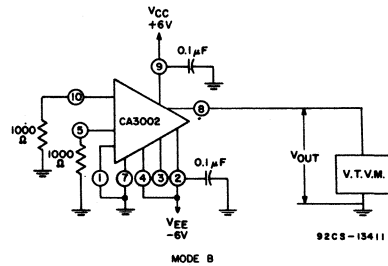
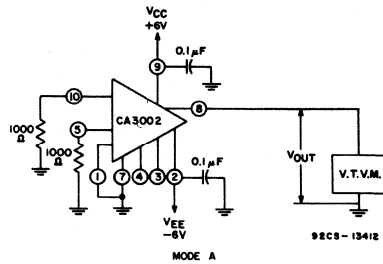


Fig. 7 – Quiescent operating voltage.

DYNAMIC CHARACTERISTICS

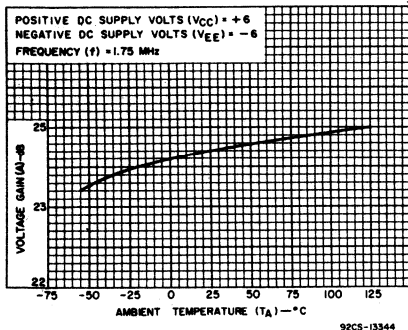


Fig. 8a – Differential voltage gain vs temperature.

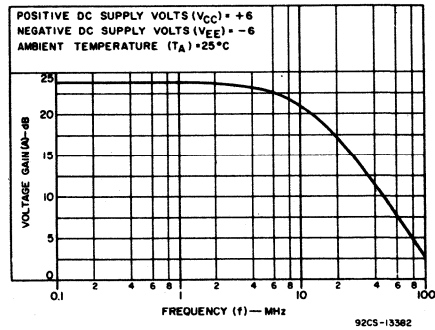


Fig. 8b – Differential voltage gain vs frequency.

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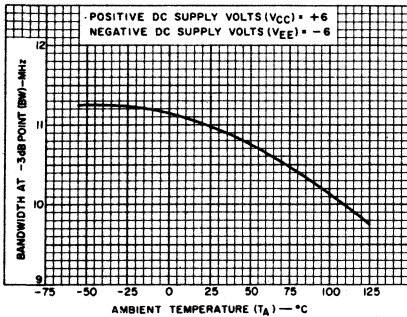


Fig. 9 - Bandwidth of -3 dB point vs temperature.

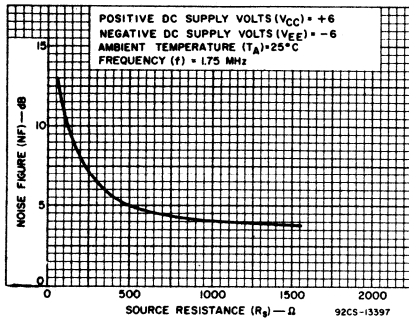


Fig. 11 - Noise figure vs source resistance.

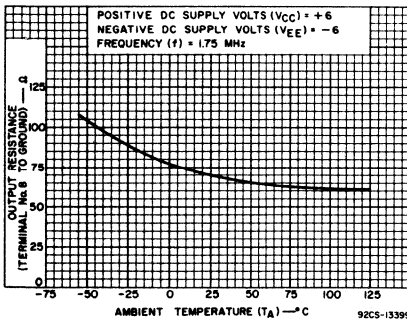


Fig. 13a - Output resistance vs temperature.

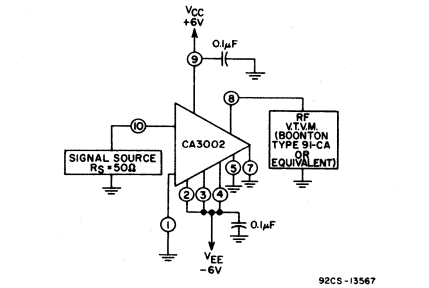
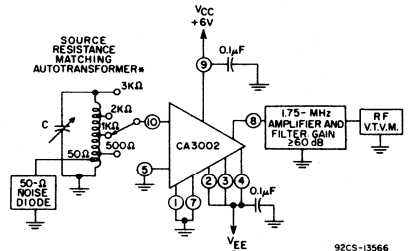


Fig. 10 - Differential voltage gain, -3 dB bandwidth, and maximum output voltage swing.



*Taps are adjusted to provide indicated equivalent values of R_s with tank tuned to resonance at 1.75 MHz, and a 50- Ω resistor connected to simulate the noise diode.

Fig. 12 - Noise figure.

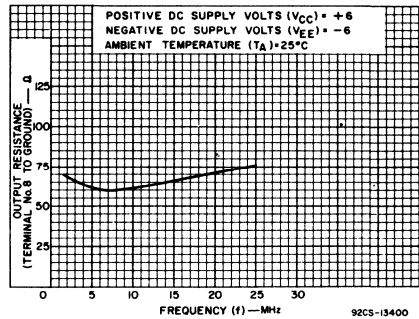


Fig. 13b - Output resistance vs frequency.

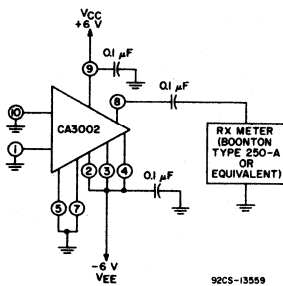


Fig. 14 - Output resistance.

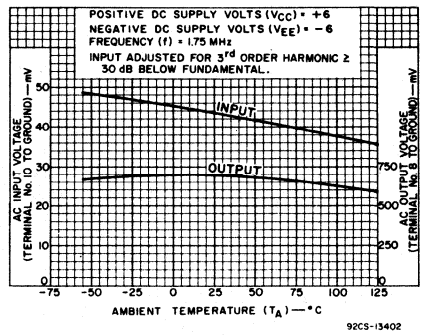
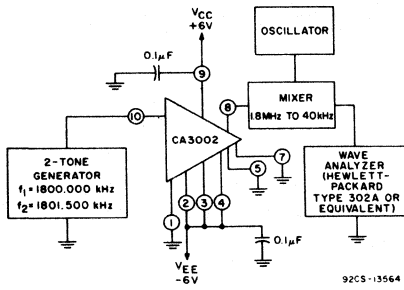


Fig. 15 - Input level for -30 dB intermodulation vs temperature.



- 1) Increase both input-signal tones until the $2f_2-f_1$ and $2f_1-f_2$ output-signal voltages are 30 dB below the f_1 and f_2 output-signal voltages.
- 2) Measure rms values of the input and output signal voltages.
- 3) The measured input signal voltage is that value when the 3rd-harmonic intermodulation products are 30 dB below the fundamental outputs.

Fig. 16 – Intermodulation circuit.

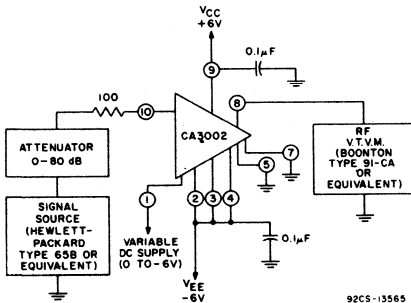


Fig. 18 – AGC range.

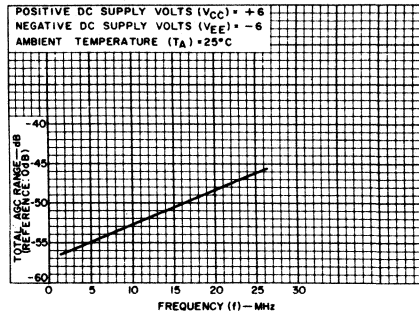
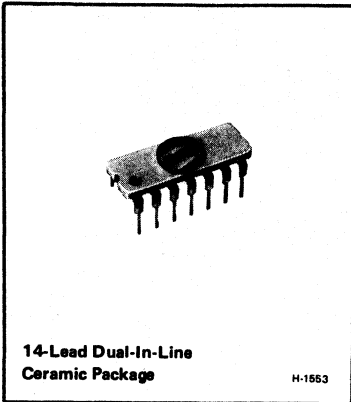


Fig. 17 – AGC range vs frequency.

- 1) Set attenuator at 80 dB attenuation.
- 2) Set variable dc supply voltage at 0 V.
- 3) Increase signal input voltage until RF V.T.V.M. indicates 5 mV output.
- 4) Set variable dc supply voltage at -6 V.
- 5) Adjust attenuator until RF V.T.V.M. again indicates 5 mV output.
- 6) Change in attenuator setting in dB is total AGC Range.

CA3091D



Four-Quadrant Multiplier

Applications:

- Multiplier ■ Divider ■ Squarer ■ Square Rooter
- Power-series approximator
- Full-wave rectifier
- Automatic level controller
- RMS converter
- Frequency discriminator
- Voltage-controlled filters and oscillators

RCA-CA3091D* a monolithic silicon integrated circuit, is a four-quadrant multiplier that provides an output voltage that is the product of two input (x and y) voltages.

This device functions as a multiplier, divider, squarer, square rooter, and power-series approximator. In addition, this device is useful in applications such as ideal full-wave rectifiers, automatic level controllers, RMS converters, frequency discriminators, and voltage-controlled filters and oscillators.

The CA3091D comprises five basic circuits (See Fig. 1), including: a multiplier block, two linearity compensators, a current converter, a current source for biasing, and a regulator (reference voltage). A brief description of the operation, functions and typical applications is given in the section "Operating Considerations". In addition there is a separate section on "Symbols, Terms, and Definitions" that defines the terms and symbols used throughout the data bulletin.

The CA3091D is supplied in 14-lead dual-in-line ceramic package and operates over the full military temperature range of -55°C to +125°C.

* Formerly Developmental Type TA5855A.

Features:*

- "Accuracy": $\pm 4\%$ (max.)
- "Linearity": 3.0% (max.)
- Feedthrough: 9 mV p-p (typ.)
- 3-db bandwidth: 4.4 MHz
- Low power operation capability: ± 6.0 V, 4 mW drain
- Low power-supply sensitivity: 36 mV/V typ.
- Smooth overload characteristics — no foldback if full-scale input signal is exceeded
- Negligible warm-up drift
- Broadband operation capability (flat to 1 MHz) — both inputs have similar characteristics for reduced high-frequency phase shift between the inputs
- Low-level linearity correction circuitry minimizes low-level feedthrough for improved small-signal accuracy
- All multiplication is performed with wideband circuitry — this permits two signals of frequencies much higher than the -3 db frequency of the multiplier to produce a difference frequency that is within the multiplier's bandwidth
- High immunity to parasitic oscillation
- Essentially free from excess peaking — provides improved frequency response
- Requires no level shifting at the output — current-source operation at the output permits output signal to be referenced to ground or other levels within the output voltage swing capabilities of the multiplier
- Internal bias regulator

MAXIMUM RATINGS; Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

DC Supply Voltages:		
Between Terms. 12 and 1	+18	V
Between Terms. 4 and 1	-18	V
DC Supply Currents:		
At Term. 12 with DC Supply Voltage = +15 V	4	mA
At Term. 4 with DC Supply Voltage = -15 V	16	mA
Bias Current (At Term. 3)	1	mA
* Input Current	± 1	mA
Output Short-Circuit Duration	No limitation	
Voltage Reference Current	10	mA
Linearity Correction Currents:		
At Terminals 7 and 8	10	mA
Device Dissipation (Up to 125°C)	200	mW
Ambient Temperature Range:		
Operating	-55 to +125	$^\circ\text{C}$
Storage	-65 to +150	$^\circ\text{C}$
Lead Temperature (during soldering):		
At distance not less than 1/32 inch (0.79 mm) from case for 10 seconds max.	+265	$^\circ\text{C}$

* External resistance is required to limit the current to the indicated ± 1 mA value.

ELECTRICAL CHARACTERISTICS, For Equipment Design

CHARACTERISTICS	SYMBOL	TEST CONDITIONS		LIMITS			UNITS
		$T_A = 25^\circ\text{C}$, $I_{IB} = 0.5$ mA $V^+ = 15$ V, $V^- = -15$ V	Circuit and/or Char. Curve	Min.	Typ.	Max.	
STATIC CHARACTERISTICS							
INPUT CIRCUIT							
Input Balance (Correction) Currents:	I_{IC}	$x = 0$	—	-20	-2.1	+20	μA
At x Input		$y = 0$	—	-20	-8.7	+20	μA
At y Input							
Feedthrough Linearity Balance (Correction) Current	I_{OC}		—	-34	-2.9	+34	μA
OUTPUT CIRCUIT							
Output Offset Current	I_{OO}	x & $y = 0$,	—	-10	-0.23	+10	μA
Output Offset Voltage	V_{OO}	I_{OO} thru $R_L = 33\text{k}\Omega$	—	-0.330	-0.0076	+0.330	V
Output Peak Current Swing	$ I_O $	Thru $R_L = 24\text{k}\Omega$	3	0.41	0.45	—	mA
Output Peak Voltage Swing	$ V_O $	Across $R_L = 33\text{k}\Omega$	4	12	12.9	—	V
DC SUPPLIES & BIASING							
Current Drain (Idling):							
At Term. 4		$V^- = -15$ V	—	—	2.9	4.5	mA
At Term. 12		$V^+ = +15$ V	—	—	2.0	3.0	mA
Reference Voltage	V_{ref}	Measured across Terms. 6 & 4 at $I = 1$ mA	—	5.5	6.1	6.7	V
DYNAMIC CHARACTERISTICS							
Output Current	I_O	With $I = 0.2$ mA at each input	—	—	0.21	0.32	mA
Normalized k Factor ($k_N = \frac{k}{k_r}$)			11	0.69	1.0	1.7	
Accuracy		Worst case at 25°C	—	—	2.6	4.0	% of
Linearity			—	—	1.7	3.0	10 V
Feedthrough Voltage:							
At $y = 20$ V p-p, $x = 0$			—	—	9	20	mV
At $x = 20$ V p-p, $y = 0$			—	—	9	20	p-p

NOTE: See page 7 for "Symbols, Terms and Definitions".

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ELECTRICAL CHARACTERISTICS, Typical Values Intended Only for Design Guidance

CHARACTERISTICS	SYMBOL	TEST CONDITIONS		TYPICAL VALUES	UNITS
		$T_A = 25^\circ\text{C}$, $I_{IB} = 0.5\text{ mA}$ $V^+ = 15\text{ V}$, $V^- = -15\text{ V}$	Circuit and/or Char. Curve		
STATIC CHARACTERISTICS					
INPUT CIRCUIT					
Input Resistance:	R_I	$ I_x \leq 0.2\text{ mA}$ $ I_y \leq 0.2\text{ mA}$	5	1.3	$\text{k}\Omega$
At x Input					
At y Input				0.5	$\text{k}\Omega$
Input Capacitance:	C_I	at 1 MHz	—	5.8	pF
At x Input					
At y Input				5.8	pF
OUTPUT CIRCUIT					
Output Resistance	R_O		6	1.0	$\text{M}\Omega$
Output Capacitance:	C_O	at 1 MHz		4.0	pF
DC Supply Voltage Sensitivity:					
At Term. 4	$\frac{\Delta V_O}{\Delta V^-}$		11	26	mV/V
At Term. 12	$\frac{\Delta V_O}{\Delta V^+}$			36	mV/V
DYNAMIC CHARACTERISTICS					
Bandwidth (At -3dB point):	BW				
Through x Input				8, 10	4.8
Through y Input			8, 9	4.4	MHz
30° Error Frequency:					
Through x Input			—	360	kHz
Through y Input				310	kHz
Maximum Slew Rate	SR	7pF in parallel with 10 M Ω load	7	27	$\text{V}/\mu\text{s}$
Temperature Coefficients:					
Output Offset Current	$\Delta I_{OO}/\Delta T$	x & y = 0	—	-0.021	$\mu\text{A}/^\circ\text{C}$
x-Input Balance Current	$\Delta I_{IC}/\Delta T$	x = 0	—	-0.063	$\mu\text{A}/^\circ\text{C}$
y-Input Balance Current		y = 0	—	-0.063	$\mu\text{A}/^\circ\text{C}$
Normalized k Factor ($k_N = \frac{k}{k_r}$)	k_N		—	-0.76	$\%/^\circ\text{C}$
Accuracy			—	0.11	$\%/^\circ\text{C}$
Linearity			—	0.06	$\%/^\circ\text{C}$
Feedthrough:					
At x = 0			—	5.6	$\text{mV}/^\circ\text{C}$
At y = 0				5.7	$\text{mV}/^\circ\text{C}$

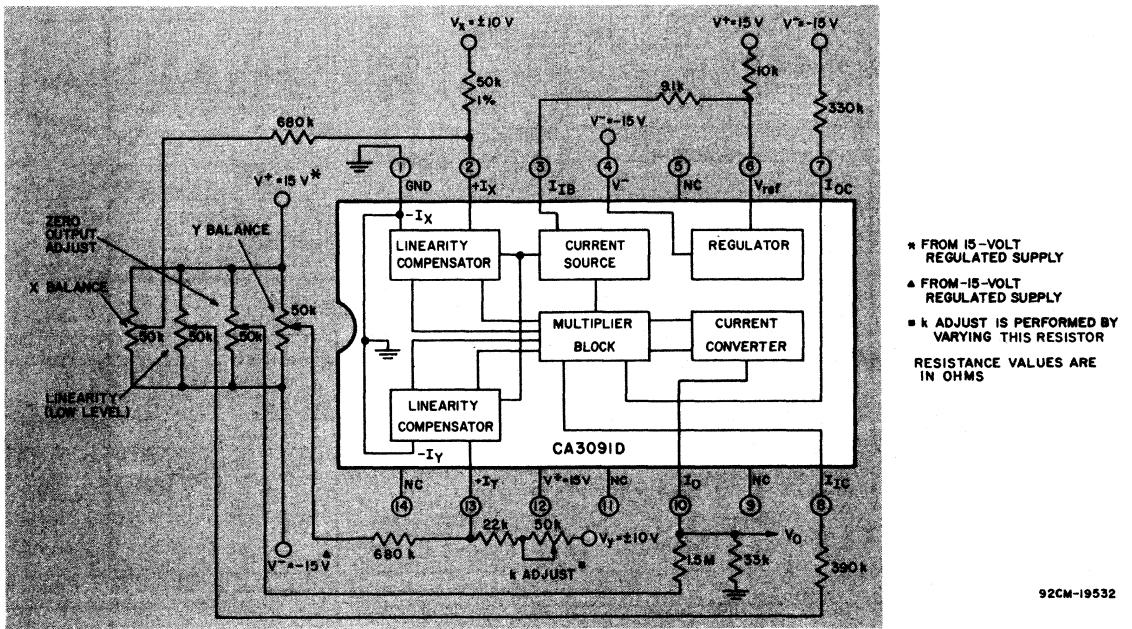


Fig.1—Functional block diagram of CA3091D with typical multiplier outboard(peripheral)circuitry.

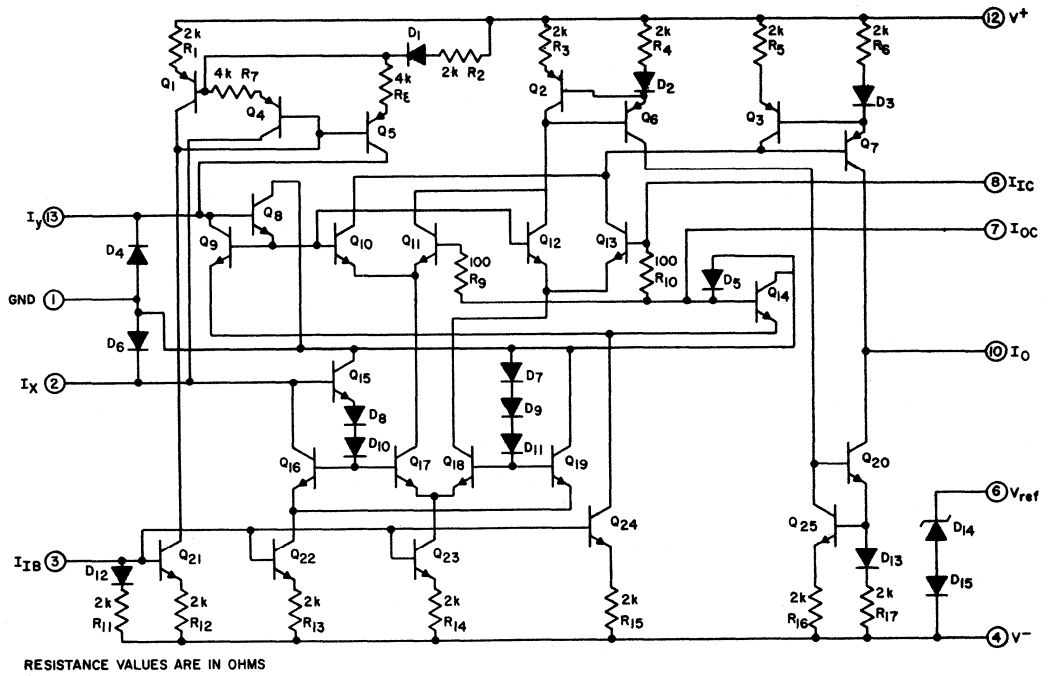


Fig.2—Schematic diagram of the CA3091D.

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CA3091D

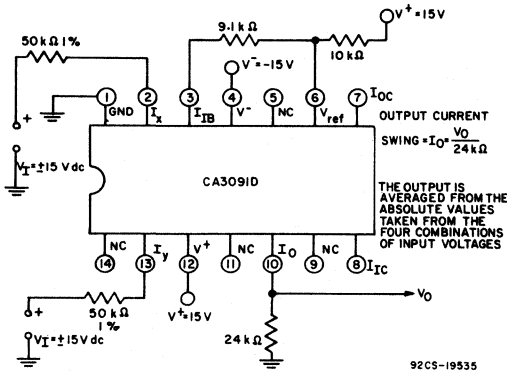


Fig. 3—Test circuit for measurement of output current swing capability.

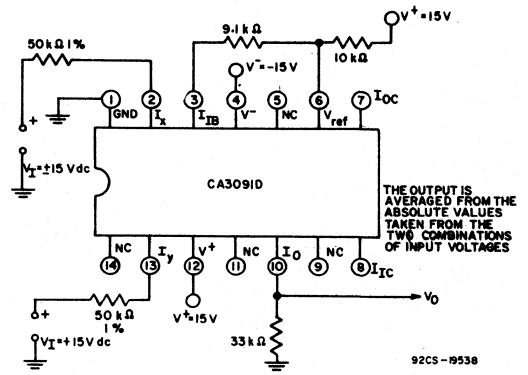


Fig. 4—Test circuit for measurement of output voltage swing capability.

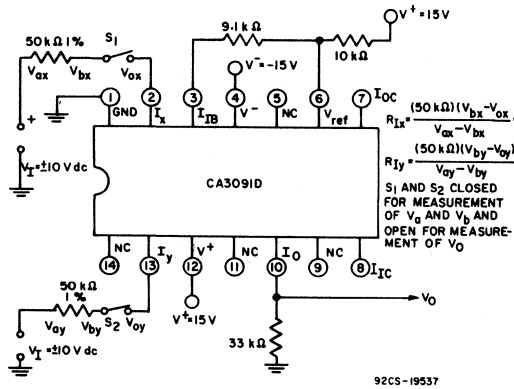


Fig. 5—Test circuit for measurement of input resistance.

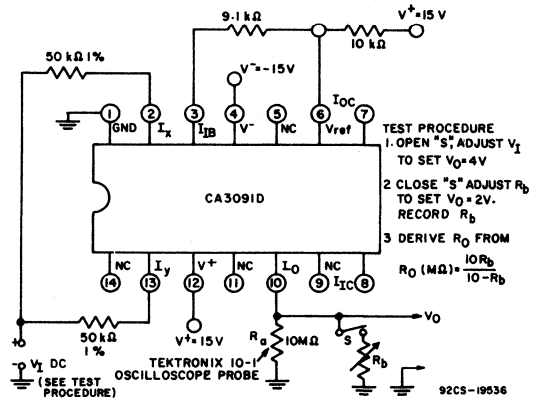


Fig. 6—Test circuit for measurement of output resistance.

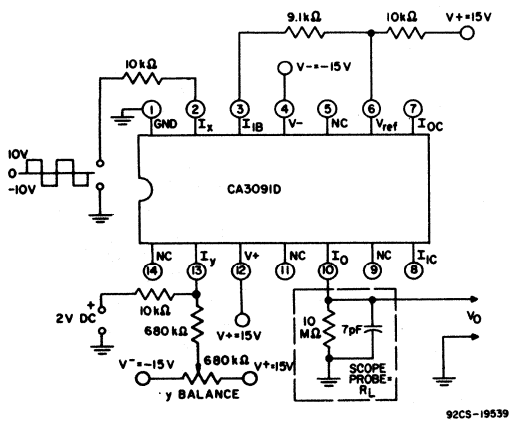


Fig. 7—Test circuit for measurement of maximum slew rate.

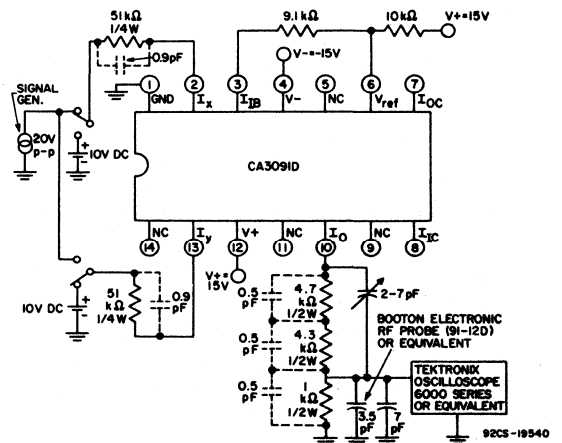
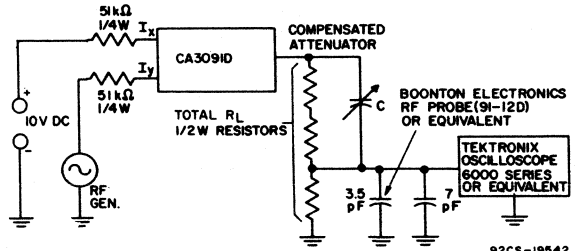
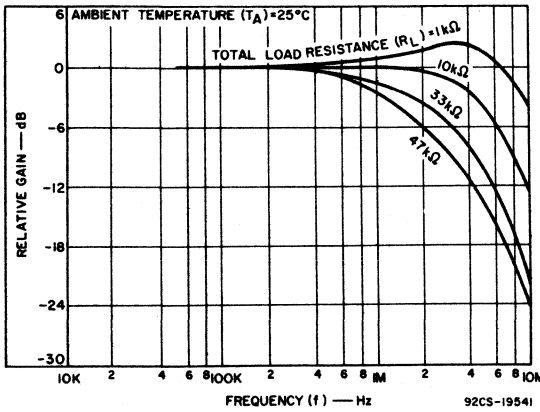
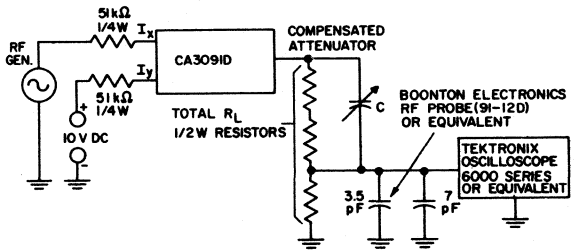
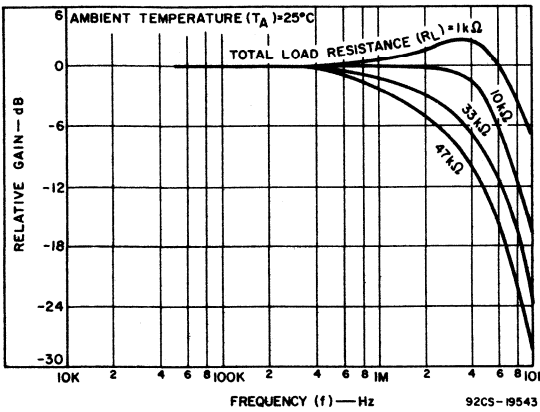


Fig. 8—Test circuit for measurement of frequency response.



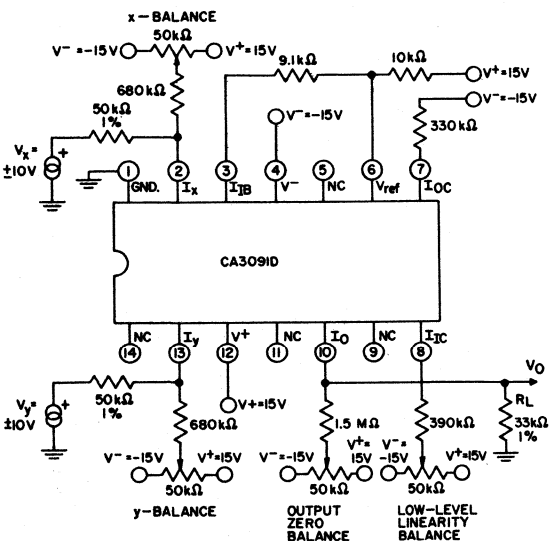
92CS-19541

Fig.9- y-input frequency response characteristic curve with associated test circuit.



92CS-19544

Fig.10- x-input frequency response characteristic curve with associated test circuit.



TEST PROCEDURES FOR MEASUREMENT OF POWER-SUPPLY SENSITIVITY

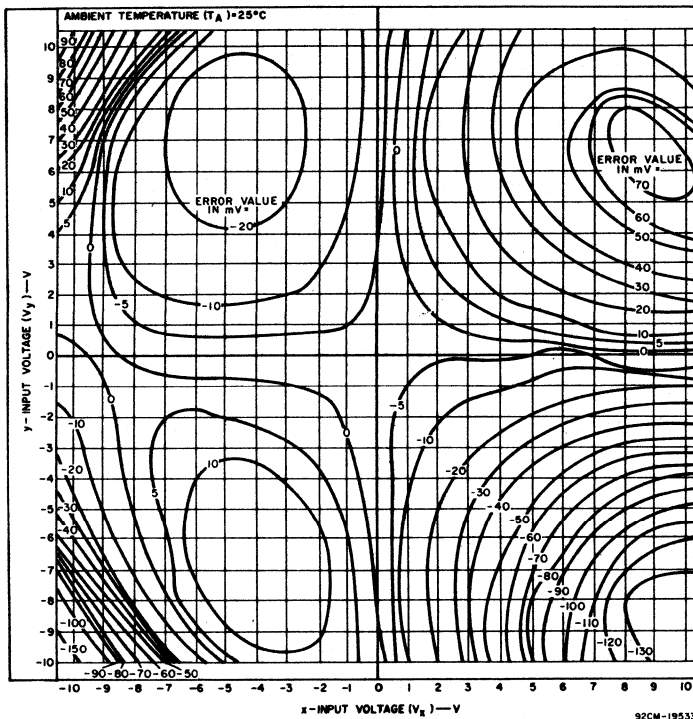
1. AT $V^+=15V, V^-=-15V$, MEASURE V_0 RECORD AS V_{01} .
2. AT $V^+=10V, V^-=-15V$, MEASURE V_0 RECORD AS V_{02} . POS. POWER SUPPLY SENSITIVITY = $\frac{V_{02} - V_{01}}{5V}$.
3. AT $V^+=15V, V^-=-10V$, MEASURE V_0 RECORD AS V_{03} . NEG. POWER SUPPLY SENSITIVITY = $\frac{V_{03} - V_{01}}{5V}$.

$k = k$ FACTOR
 $k_r = 0.1$ REFERENCE OR ADJUSTED k FACTOR
 $k_N = k/k_r = 0.1 V_0 =$ NORMALIZED k FACTOR (i.e. $k_N = 1$, IF $V_k = V_y = V_0 = 10$)
 OUTPUT CURRENT (mA) [AT A CURRENT OF 0.2 mA AT BOTH INPUTS] = $V_0 / 33k\Omega$
 OUTPUT VALUES ARE AVERAGED FOR 4 COMBINATIONS OF INPUTS ($k_I = \frac{V_0}{R_L} = \frac{V_0}{33k\Omega}$)
 $(0.2 \times 10^{-3})^2$

92CS-19545

RESISTORS HAVE A TOLERANCE OF 5% UNLESS OTHERWISE INDICATED

Fig.11-Test circuit for measurement of current gain and power-supply sensitivity.



Note: See "Contour Map" in "Symbols, Terms and Definitions" Section.

Fig.12—Contour mapping of multiplier accuracy (plotted on isomers) and linearity.

SYMBOLS, TERMS AND DEFINITIONS

Output Offset Current

The multiplier output current produced when both of the multiplier input signals are in the zero state.

Output Zero

Sets the output at the zero level when the x and y inputs are in the zero state. (It is implied that all other zeroing adjustments have been effected.)

R_I

Input Resistance — Converts the input voltage to an input current.

R_L

Output (Load) Resistance — Converts the output current to a voltage.

R_O

Output Resistance — See V_O and I_O for the equations associated with these properties.

Regulator Diode

A temperature compensated Zener diode, included in the multiplier circuit, to provide a stable I_{1B}.

Scale Factor or k factor (k)

Represents the basic gain of the multiplier as expressed in the equation $V_O = kV_xV_y$

The equation indicates the ideal transfer function for the multiplier. The normalized k factor is expressed by $k_N = k/k_{ref}$

where k_{ref} is the ideal or reference k factor. The ideal factor, k_{ref} is the value at which the k factor is set when the k-factor adjust control is trimmed. Optimum operation of the CA3091D is achieved when the k-factor is 0.1.

V_{IM}

The maximum ac sine-wave voltage to be applied to the multiplier; a 20-volt p-p sine wave is the nominal maximum swing voltage recommended for use with 50-kilohm input resistors.

V_{MID}

An ac or dc voltage that approximately satisfies the equation

$$V_{MID} = V_{IM} / \sqrt{2}$$

V_O

The output product voltage derived from the expression

$$(kV_xV_y = V_O)$$

V_{ref}

Temperature compensated zener connected to the -15 volt supply to provide a reference voltage as an aid in setting up a stable I_{1B}.

V_x, V_y

The input voltages to be multiplied.

x-Balance Circuit

Sets the output to the zero level when the x-input is in the zero state.

y-Balance Circuit

Sets the output to the zero level when the y-input is in the zero state.

SYMBOLS, TERMS AND DEFINITIONS – continued

Accuracy

Accuracy defines the degree of error encountered in the operation of the multiplier. It is portrayed on a contour map by isomers (contour lines). Isomers with the highest values indicate "less-accurate" operation of the multiplier. (See illustrative Contour Map in Fig. 12.)

Contour Map

The contour map, shown in Fig. 12, is a graphical portrayal of the multiplier errors in the x, y input plane. Each contour line, termed "isomer", connects those points whose error values (in millivolts) are equal in magnitude. For example, a -20 mV contour line with points at $V_x = 5V$ and $V_y = -3V$ indicates that the output voltage is 20 mV less than the theoretical output product (kV_xV_y). This error voltage, presented in percent of full-scale input ($\pm 10 V$), defines the "accuracy" of the device. Thus, a 20-mV error voltage represents an "accuracy" of 0.2% as derived from the equation:

$$\text{Accuracy} = 20 \text{ mV}/10 \times 100\% = 0.2\%.$$

A contour map provides a true indication of multiplier performance in each of the four quadrants. Each CA3091D is comprehensively tested and must provide the specified accuracy in the four quadrants.

Current Converter

This portion of the IC combines the multiplier's differential-amplifier output currents and converts them to a single-ended output current.

Current Sources

These circuits provide the biasing currents for the various circuits in the IC. The I_{IB} terminal provides the control current for the current-source circuit.

Feedthrough

Feedthrough occurs when an output signal is produced even though one of the input signals is zero. Consequently, feedthrough signal characteristics constitute a source of error in the operation of a multiplier. In the CA3091D, for example, the feedthrough signal output is specified to be less than 20 mV p-p when either terminal is set at 20 V p-p and the other terminal is set to zero.

 I_{IB}

Circuit biasing control current.

 I_{IC}

See I_{OC} .

 I_O

Output product current ($k_1 I_x I_y = I_O$), where $k_1 = kR_1^2 / R_L$

 I_{OC}, I_{IC}

Compensatory input and output currents required to correct nonlinearity along the x axis. (Optional for low-level signal use.)

 I_x, I_y

Input currents to be multiplied.

k

Voltage Scale Factor (determines the gain of the multiplier).

 k_1

Current Scale Factor ($k_1 = (R_1^2 / R_L)k$).

k adjust

Scale-Factor Adjustment.

Linearity

"Linearity" indicates the degree of multiplier error (i.e. deviation from "straight-line" characteristics) along each of the four boundaries of the input x, y field. These boundaries are formed when one input is held at one of the two maximum values (10 volts or -10 volts) and the other input is swept through the voltage range. (See Contour Map for additional information.)

Linearity Adjust

An external circuit to provide vernier adjustment for optimum linearity. This control should be adjusted before adjusting the y-balance control.

Linearity Balance Circuit (Low-Level)

This circuit makes the multiplier's transfer function linear for low-level x-input signals.

Linearity Compensator

Internal circuitry that converts input current into a non-linear voltage, a requisite for producing a linear output in the differential amplifiers of the multiplier circuit.

Multiplier Circuitry

Provides the product of the two input voltages.

Multiplier Transfer Function

This function mathematically describes the interaction of the two inputs and the resulting output signal. The basic transfer function for a multiplier is

$$k(V_x + V_{xe})(V_y + V_{ye}) = V_o + V_{oe}$$

where: k = k factor and represents the basic gain of the multiplier

V_x, V_y = the external inputs to be multiplied

V_o = the desired value of the product output signal

V_{xe}, V_{ye} = the "effective" errors that occur at the inputs of the multiplier and cause an output signal when either input is in a zero state.

V_{oe} = the error voltage that develops at the output of the multiplier

DC correction factors are added to the multiplier inputs and output to compensate for the errors and offset variations. A complex linearity error term appears in the transfer function; however, this term is not included in the above equation for the purpose of clarity.

CA3091D

OPERATING CONSIDERATIONS

Operation of a Multiplier

A multiplier is, essentially, a gain-controlled amplifier (See Fig. 13) that multiplies the input signal (V_x) with the external gain controlling signal (V_y) to produce the resultant output (V_o). The gain is externally adjustable by a coefficient (k). Stated simply, a multiplier produces an output voltage that is the linear product of two input voltages.

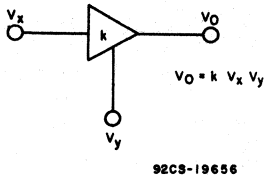
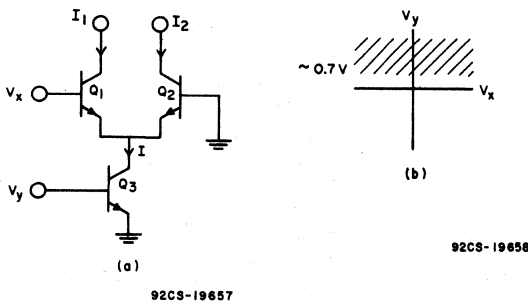


Fig. 13—Gain-controlled amplifier.

The basic multiplier, shown in Fig. 14a, is a two-quadrant multiplier. The input signal (V_x) may have either a positive or negative polarity whereas, the external gain-controlling signal (V_y) must be positive and greater than the base-to-emitter voltage (Fig. 14b). The output current ($I_1 - I_2$) of the differential amplifier, comprised of transistors Q1 and Q2, is related to both the input signal (V_x) and the current source (I). Since the current source (I) is related to the gain controlling signal (V_y) the output current ($I_1 - I_2$), therefore, is related to both V_x and V_y .



a) Basic circuit.

b) Multiplier functional only in shaded region.

Fig. 14—Two-quadrant multiplier.

This relationship is essentially non-linear; thus an appropriate linearization circuit must be provided in the input stage to achieve the following linear relationship:

$$I_1 - I_2 = k' V_x V_y \quad (\text{Eq. 1})$$

where k' is a constant

Figure 15 shows a typical arrangement of three differential amplifiers to form a four-quadrant multiplier. This arrangement incorporates the operating principles of the two-quadrant multiplier, but, in addition, it permits both of the input signals (V_x and V_y) to have positive or negative polarities (or zero). When either input is zero, the output current ($I_1 - I_2$) must, theoretically, be zero as is shown by the following:

1. Assume $V_x = 0$,
 then $i_1 = i_2$ and $i_3 = i_4$
 therefore $i_1 + i_4 = i_2 + i_3$.
 Since $I_1 = i_1 + i_4$ and $I_2 = i_2 + i_3$,
 then $I_1 = I_2$.
 This equality is independent of V_y
2. Now assume $V_y = 0$,
 then $i_5 = i_6$.
 Since $i_5 = i_1 + i_2$ and $i_6 = i_3 + i_4$,
 then $i_1 + i_2 = i_3 + i_4$.
 Since $i_1 = i_3$ and $i_2 = i_4$
 then $i_1 + i_4 = i_3 + i_2$.
 Therefore $I_1 = I_2$.
 This equality is independent of V_x .

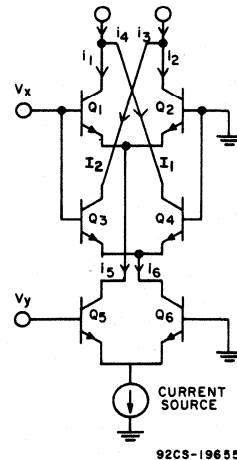


Fig. 15—Basic four-quadrant multiplier.

The multiplying operation discussed in the previous section applies when neither V_x nor V_y is zero. The output current ($I_1 - I_2$) then satisfies Equation 1,

$$I_1 - I_2 = k' V_x V_y.$$

The multiplying action of the four-quadrant multiplier is dependent on current unbalance in the three differential amplifiers. Ideally, the multiplying operation should not occur if either V_x or V_y is 0. However, in practical applications slight current unbalances do exist. It is necessary, therefore, to null out such unbalances with external potentiometers prior to operation.

TYPICAL OPERATING CONSIDERATIONS

The RCA-CA3091D, shown in Fig. 2, is a four-quadrant multiplier that incorporates the basic multiplier principle, previously discussed in "Operation of a Multiplier". Because the design of this multiplier is based on the multiplication of two input currents to produce an output current it is necessary to convert the input voltages to input currents and the output current to an output voltage by inserting resistors at both input and output terminals. Fig. 1 shows the four-quadrant multiplier with its peripheral circuitry for nulling current unbalances.

The Bias Current (I_B) at Term. 3 sets the operating current level for the entire multiplier circuit by means of a current-source circuit. Therefore, it is essential that this bias current level remain constant under all operating conditions. To maintain this steady state, a temperature compensated zener diode is provided on the chip and connected to the Reference Voltage (Term.6).

Linearity of the differential amplifier transconductance function is accomplished by linearity compensators as shown

in Fig. 1. To correct low-level signal unbalances that may occur between Differential Amplifiers A and B, an external potentiometer is connected to Terminals 7 and 8 (See Fig. 1). The Current Converter circuit, which consists of a set of current mirrors, supplies the output current ($I_1 - I_2$). It is important that circuit unbalances be corrected prior to operation. Table I describes the alignment procedures for correcting these unbalances.

A multifunctional circuit board (Figs. 16 and 17) is available for performing the four basic applications, such as, multiplying, dividing, squaring and taking the square root.

When the CA3091D is used as a multiplier (Fig. 18) or as a squarer (Fig. 18) only the basic peripheral circuitry on the multifunctional circuit board is utilized and the general-purpose operational amplifier (CA3741T) is disabled from operation. Follow the ac alignment procedures for these two applications before operating the circuit.

When the CA3091D is used as a divider (Fig. 20), the operational amplifier is required in order to provide the proper negative feedback. The limitations for operation as a divider are that $0 < V_y \leq 10V$ and $-10V \leq V_z \leq 10V$. Note, the range of V_y is limited to the positive polarity; if V_y was permitted to go negative, the feedback loop would go positive and, thereby, create an unstable operating condition.

Alignment of the divider (Fig. 19) differs from multiplier and squarer alignment because of the additional variances introduced by the operational amplifier. A coupling capacitor is

Table I

AC Alignment Procedures For CA3091D, Four-Quadrant Multiplier
(Refer to Fig. 16, for circuit pertaining to following alignment procedures.)

Step No.	Voltage Setting		Control Adjust	Test Equipment Used	Measure	Notes
	V_x	V_y				
1	—	—	—	—	—	Set all potentiometers to center of range.
2	0	V_{IM}	x Balance	AC VM	V_O	Adjust for a minimum reading.
3	0	V_{IM}	Linearity	AC VM	V_O	Adjust for a minimum reading.
4	—	—	—	—	—	Repeat Steps 1 and 2 until no further improvement is noted.
5	V_{IM}	0	y Balance	AC VM	V_O	Adjust for a minimum reading.
6	0	0	Zero Output	DC VM	V_O	Adjust for zero output.
7	V_{MID}	V_{MID}	R_k	AC/DC VM	V_O	Adjust for $V_{MID}^2/10$ at the output.
8	—	—	—	—	—	Check multiplier for alignment in all four quadrants.

V_{IM} — Is the maximum AC swing of the sine wave that will be applied to the multiplier. A 20-volt p-p value is the nominal maximum swing of the AC sine wave with input resistors of 50 kilohms.

V_{MID} — An AC or DC voltage that approximately satisfies the equation $V_{MID} = V_{IM}/\sqrt{2}$. For example, if a 50-kilohm resistor is used with a 7-volt input, then R_k should be adjusted for a 4.9-volt output.

Linear Integrated Circuits

CA3091D

provided at the output of the divider alignment circuit in order to separate the ac signal from the dc signal and, thus, avoid interaction between the calibrating potentiometers.

The alignment procedure for the square-rooter function (Fig. 21) is identical to the alignment procedure for the divider function. The input voltage range is limited to $0 < V_I \leq 10V$. This limitation is necessary in order to prevent the output voltage (V_O) from latching to the negative output saturation voltage of the operational amplifier. Table II describes the divider alignment procedure.

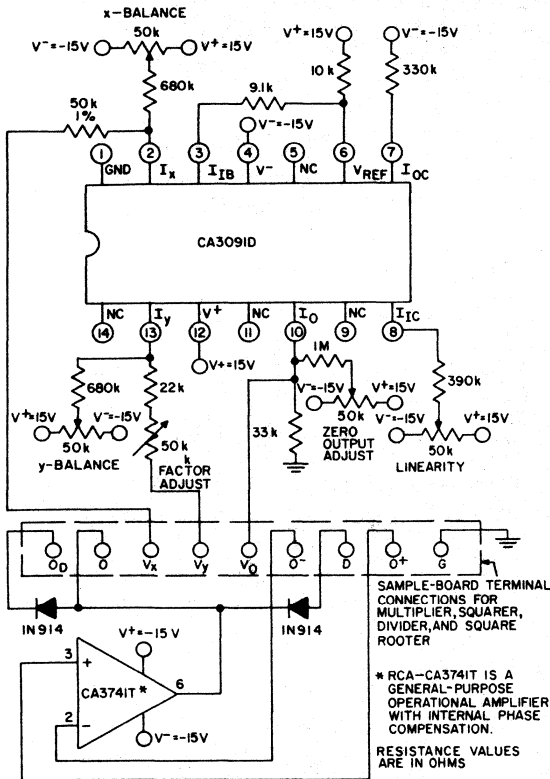
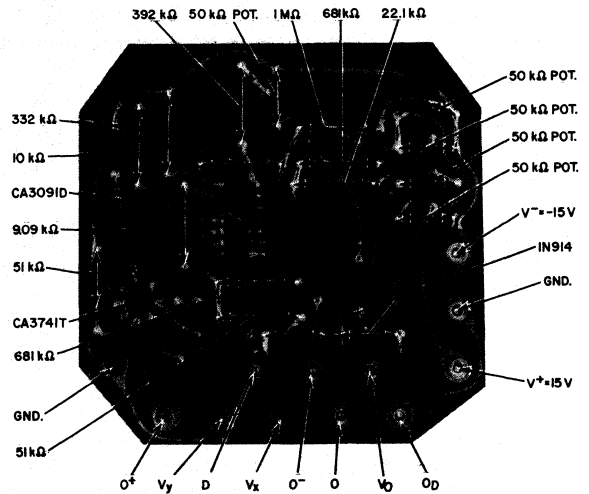
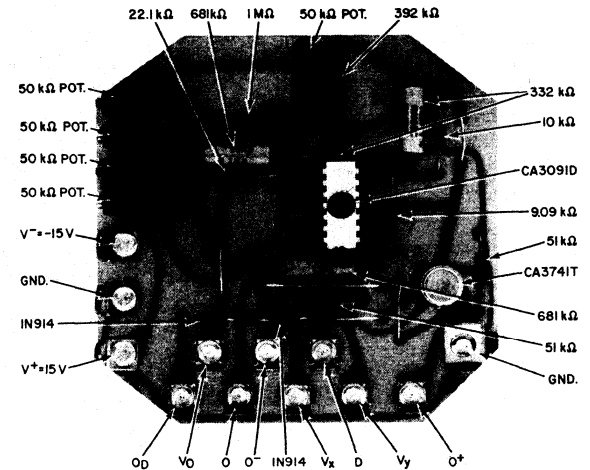


Fig.16—Typical multifunction circuit arrangement utilizing the CA3091D and CA3741T.



a) Foil side.

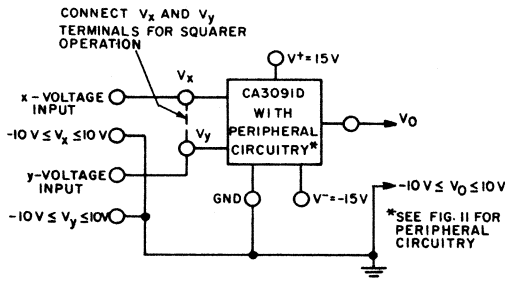


b) Component side.

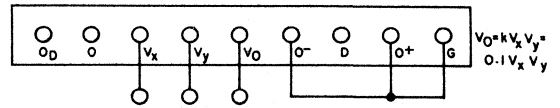
Fig.17—Photographs of a printed-circuit board for multi-function applications (multiplier, squarer, divider, square rooter) utilizing the CA3091D and CA3741T.

Table II — Divider Alignment Procedure

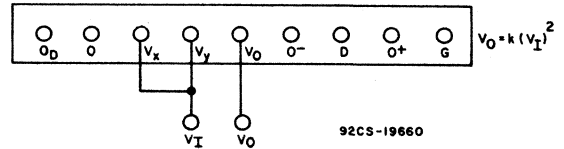
Step No.	Set		Measure	Output Coupling	Test Equipment Used	Adjust	Notes
	V_z V	V_y V					
1	—	—	—	—	—	—	Set all potentiometers to center of range.
2	0	V_S	V_O	ac	ac - VM	Ozero	Adjust for minimum reading.
3	0	10V dc	V_O	dc	dc - VM	xbalance	Adjust for 0V dc output.
4	V_S	V_S	V_O	ac	ac - VM	ybalance	Adjust for minimum reading.
5	5V dc	5V dc	V_O	dc	dc - VM	kadjust	Adjust for 10V dc output.



a) Circuit arrangement for multiplier or squarer operation.



b) Terminal connections for multiplying operation.



c) Terminal connections for squarer operation.

Fig.18—Multifunction circuit-board arrangement with terminal connections for multiplier and squarer operation.

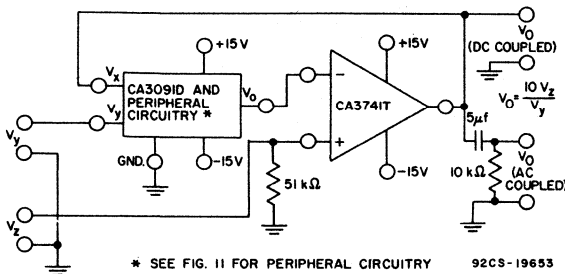


Fig.19—(a) Divider alignment circuit.

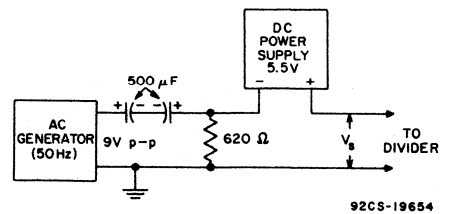
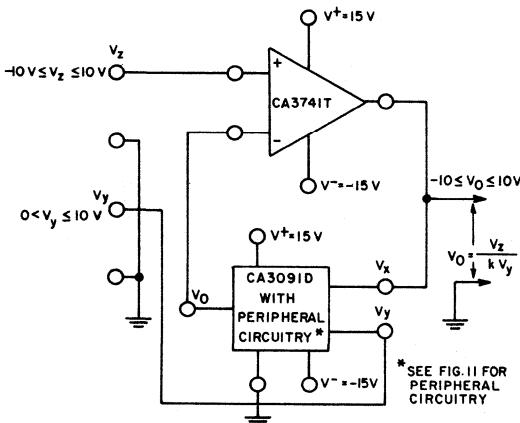
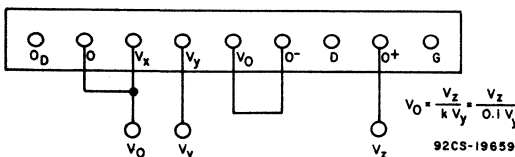


Fig.19—(b) Circuit to provide offset ac signal for use in divider alignment procedure.

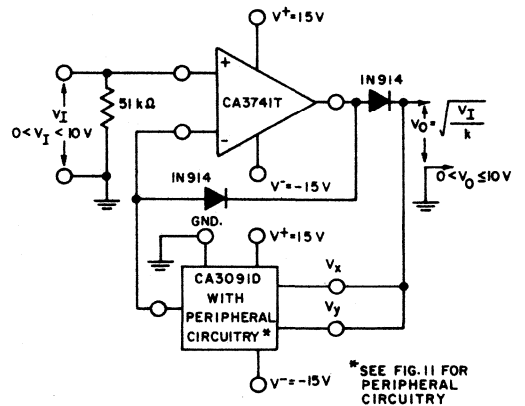


a) Circuit arrangement for divider operation.

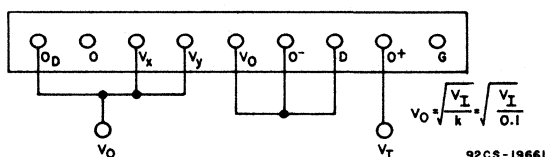


b) Terminal connections for divider operation.

Fig.20—Multifunction circuit-board arrangement with terminal connections for divider operation.

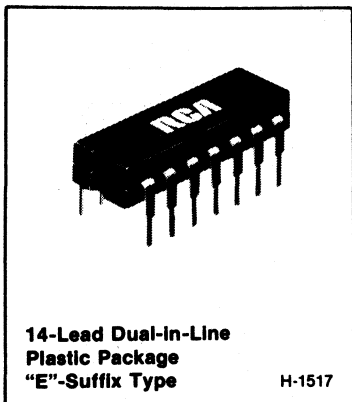


a) Circuit arrangement for square-rooter operation.



b) Terminal connections for square-rooter operation.

Fig.21—Multifunction circuit-board arrangement with terminal connections for square-rooter operation.



1.25 GHz Prescaler

For Industrial Applications

FEATURES:

- Broadband operation - DC to 1.25 GHz
- High sensitivity
- Standard T²L or ECL power supply
- Dual mode operation - VHF/UHF (÷ 64/ ÷ 256)
- Complementary ECL outputs
- Independent VHF and UHF input terminals

The RCA-CA3179E is an integrated-circuit prescaler intended for use in communications and instrumentation systems. It performs division by 256 in the uhf mode and division by 64 in the vhf mode.

The mode of operation is selected by means of the bandswitch and the separate uhf and vhf input terminals provided. Either single- or double-ended inputs can be applied. These inputs are normally ac coupled, but dc coupling can be used if the specified bias levels are maintained. The output is a complementary emitter-coupled stage capable of driving a 33-pF or equivalent load. The harmonic output is reduced above 40 MHz by limiting output-signal rise and fall times and by maintaining a balanced load.

In the uhf mode, which is activated by applying a high level (logical 1) to the bandswitch input terminal, all eight divider stages are operative, resulting in division by 256. In the vhf mode, activated by a low level (logical 0) at the vhf input terminal, two divider stages are bypassed, resulting in division by 64. An internal amplifier/multiplexer provides this control while isolating both inputs, amplifying the input signal, and improving sensitivity.

The CA3179E is supplied in the 14-lead dual-in-line plastic package.

Applications:

- Digital frequency synthesizers for:
 - VHF/UHF receivers
 - Satellite communications
 - Instrumentation
- High-frequency divider for:
 - UHF frequency counters
 - UHF timers
 - High-speed computers
 - Frequency standards
 - SHF second IF local-oscillator injection
 - PCM communications
 - Satellite communications
 - Radar ranging systems
- High-frequency up-converters

Table of Absolute-Maximum Ratings

Term. No.	Min. Volts	Max. Volts	Max. I _{IN} (mA)	Max. I _{OUT} (mA)
1 & 2*	0	5.5	110	0
3	-0.3	20	1	1
4 & 5	—	—	0.1	10
9, 10, 13, 14 [▲]	—	4	0.1	1

*Terms. 1 & 2 tied together.
[▲]Maximum rf drive = 500 mVRMS.
 Terms. 7 & 8 are system ground and tied together.
 Terms. 6, 11, 12 = no connection.

CA3179E

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE	5.5 V
DC BANDSWITCH VOLTAGE	20 V
RMS INPUT VOLTAGE	0.5 V
DEVICE DISSIPATION:	
UP TO $T_A = 70^\circ\text{C}$	700 mW
ABOVE $T_A = 70^\circ\text{C}$	derate linearly at 11.1 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:	
OPERATING	0 to 85 $^\circ\text{C}$
STORAGE	-55 to +150 $^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
AT DISTANCE 1/16 \pm 1/32 INCH (1.59 \pm 0.79 MM)	
FROM CASE FOR 10 SECONDS MAX.	+265 $^\circ\text{C}$

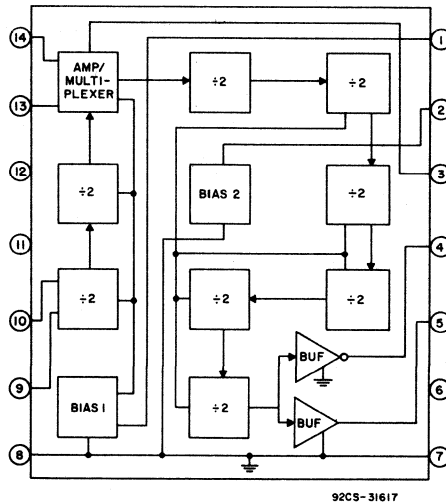


Fig. 1 - CA3179G block diagram.

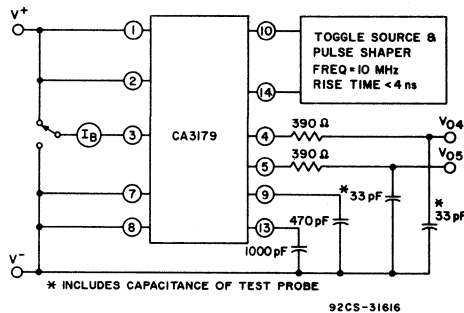


Fig. 2 - DC characteristics test circuit.

Special Function Circuits

CA3179E

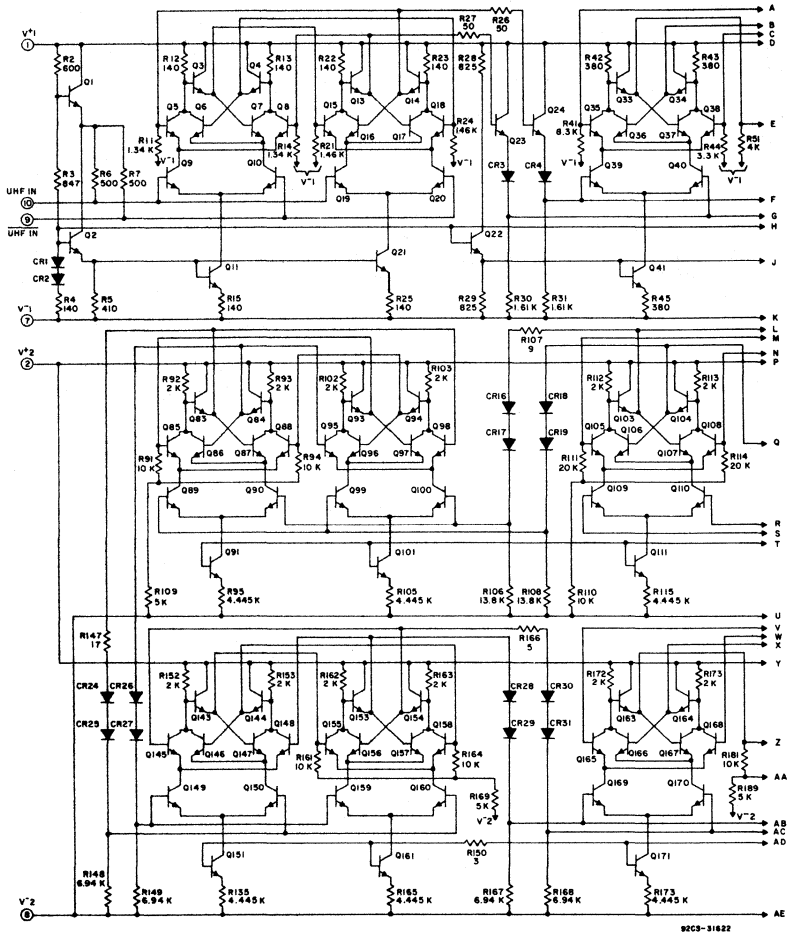


Fig. 3 - Schematic diagram (cont'd on next page).

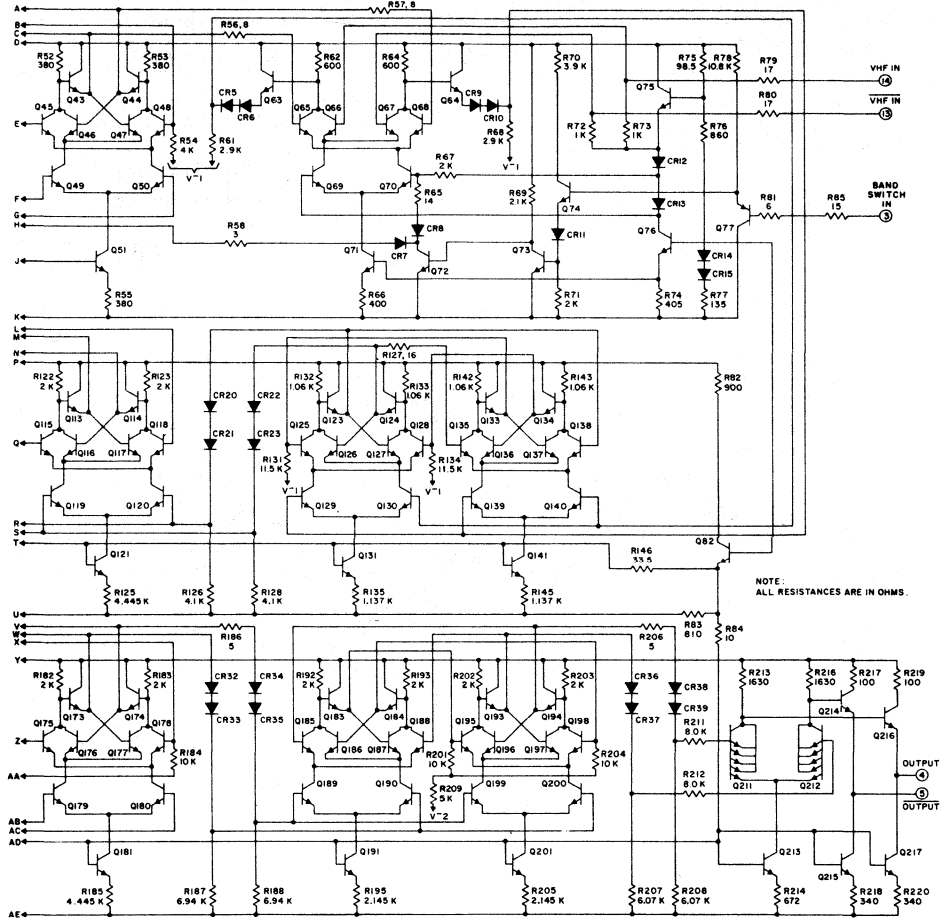


Fig. 3 - Schematic diagram (cont'd from previous page).

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V^+ = 5\text{ V}$, $V^- = 0\text{ V}$

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS	
		Min.	Typ.	Max.		
<i>Static (See Fig. 2)</i>						
Supply Current, I^+	Terms. 1 & 2	30	65	100	mA	
Bandswitch Voltage:	Term. 3	Low, V_{BL}	2.4	—	—	V
		High, V_{BH}	—	—	0.8	
Bandswitch Current:	$V_3 = 0\text{ V}$	Low, I_{BL}	-1	—	—	mA
		High, I_{BH}	—	—	0.5	
<i>Dynamic (See Fig. 4)</i>						
Sine Wave Sensitivity (Single-ended)	$f_{IN} = 450\text{ to }950\text{ MHz}$ $V_3 = 5\text{ V}$	0	30	80	mVRMS	
	$f_{IN} = 80\text{ to }450\text{ MHz}$ $V_3 = 5\text{ V}$	—	50	160		
	$f_{IN} = 90\text{ to }275\text{ MHz}$ $V_3 = 0\text{ V}$	—	5	40		
Output Voltage:	Term. 4 or 5	High, V_{OH}	—	4.2	—	V
		Low, V_{OL}	—	3	—	
		Peak-to-Peak, V_{OP-P}	0.65	1.1	1.6	
Output Rise or Fall Time, t_r, t_f		40	70	110	ns	
Internal Bias	Term. 13 or 14	$(V_{DD} - 1)$			V	
	Term. 9 or 10	$(V_{DD} - 2.7)$				
DC Input Resistance, R_i	Term. 13 to 14	2000			Ω	
	Term. 9 to 10	1000				
Complex Input Impedance	Term. 9 to 10, $V_{IN} = 100\text{ mV}$, $f_{IN} = 950\text{ MHz}$	20			Ω	
	Term. 9 to 10, $V_{IN} = 100\text{ mV}$, $f_{IN} = 450\text{ MHz}$	$30 - j80$				
	Term. 13 to 14, $V_{IN} = 100\text{ mV}$, $f_{IN} = 275\text{ MHz}$	$35 - j100$				

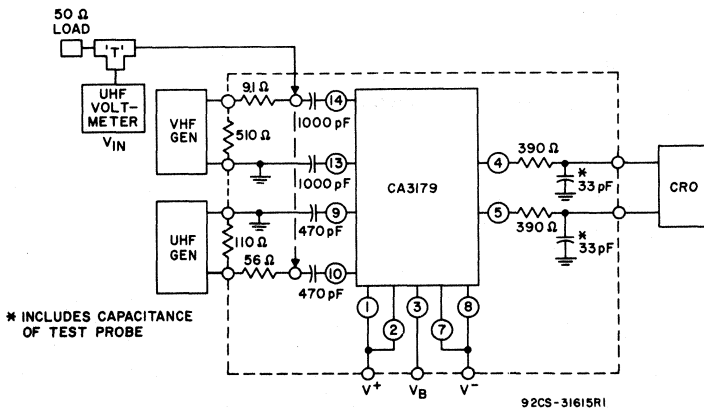


Fig. 4 - AC characteristics test circuit.

CA3179E

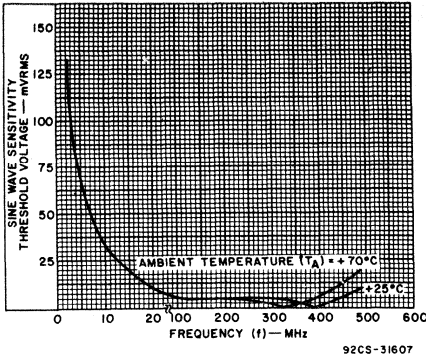


Fig. 5 - Typical threshold sensitivity in the +64 VHF mode.

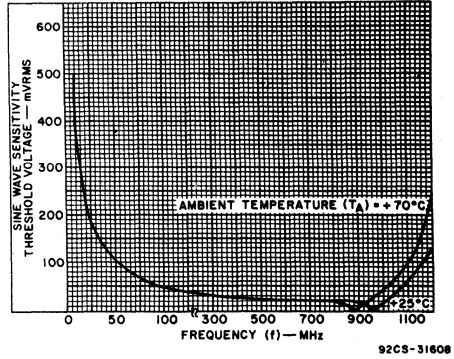


Fig. 6 - Typical threshold sensitivity in the +256 UHF mode.

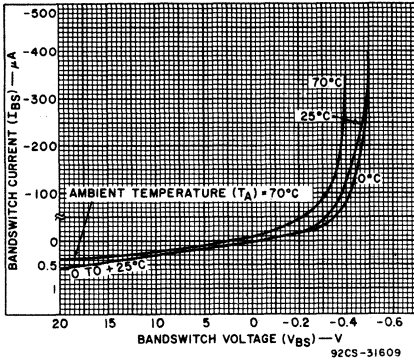


Fig. 7 - Typical bandswitch current as a function of bandswitch voltage and ambient temperature.

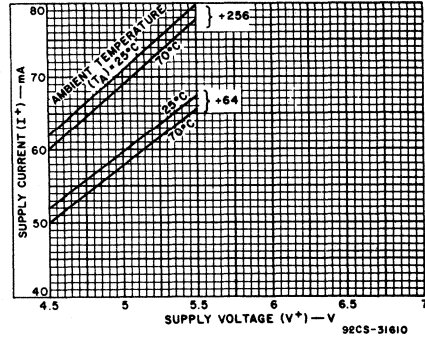


Fig. 8 - Supply current as a function of supply voltage and ambient temperature.

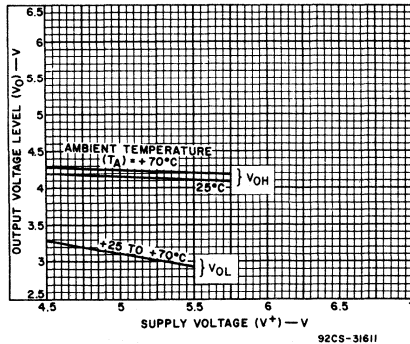
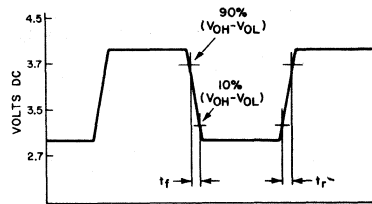


Fig. 9 - Typical output voltage level as a function of supply voltage and ambient temperature.



OUTPUT PULSE = 0.65 V_{p-p} MIN., 1.6 V_{p-p} MAX.
 t_r, t_f = 40 ns MIN., 110 ns MAX.

92CS-31613

Fig. 10 - Output pulse characteristics.

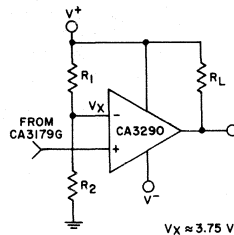
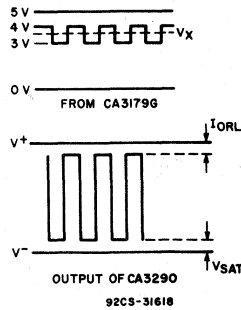


Fig. 11 - Typical bipolar interface circuit.



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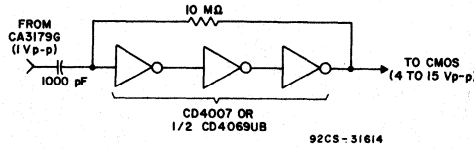
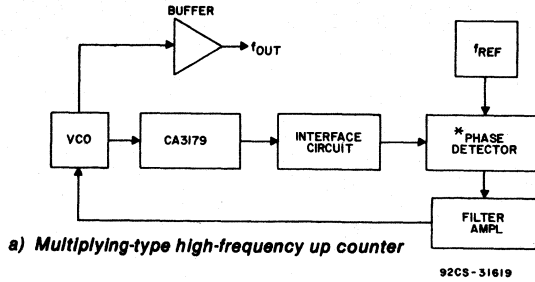
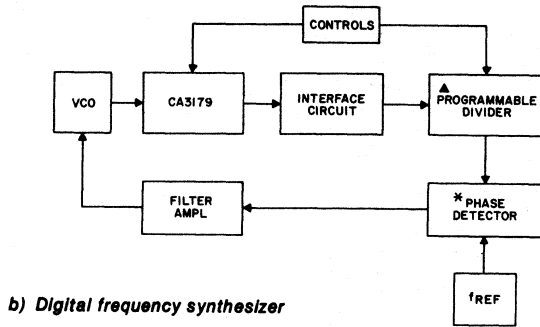


Fig. 12 - Typical CMOS interface circuit.



a) Multiplying-type high-frequency up counter



b) Digital frequency synthesizer

* CD4046A/B, CD4030A/B, CD4070A/B OR EQUIVALENT
 ▲ CD4018B, CD4029B, CD4059A, CD40102B, CD40103B OR EQUIVALENT
 92CS-31620

Fig. 13 - Typical system configuration.

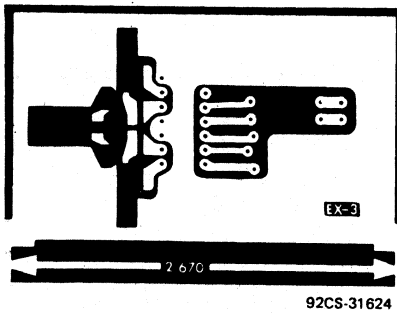


Fig. 14 - Printed-circuit board for the dynamic test circuit.

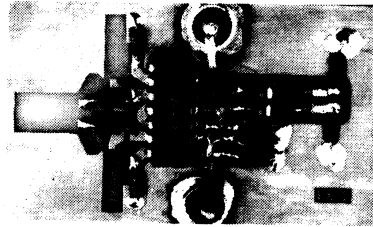
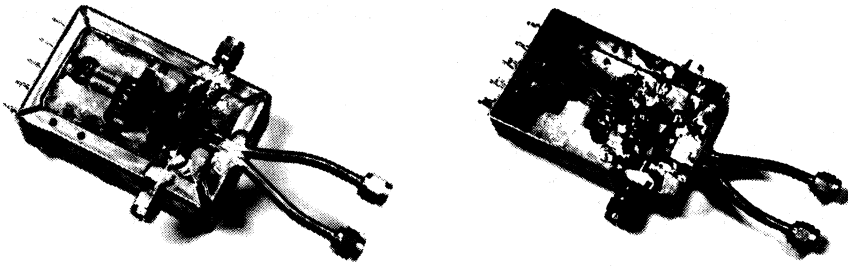


Fig. 15 - Printed-circuit board for the dynamic test circuit with components.

CA3179E



TOP VIEW

92CS-31652

BOTTOM VIEW

92CS-31653

Fig. 16 - Dynamic test circuit fixture.

IMPEDANCE COORDINATES

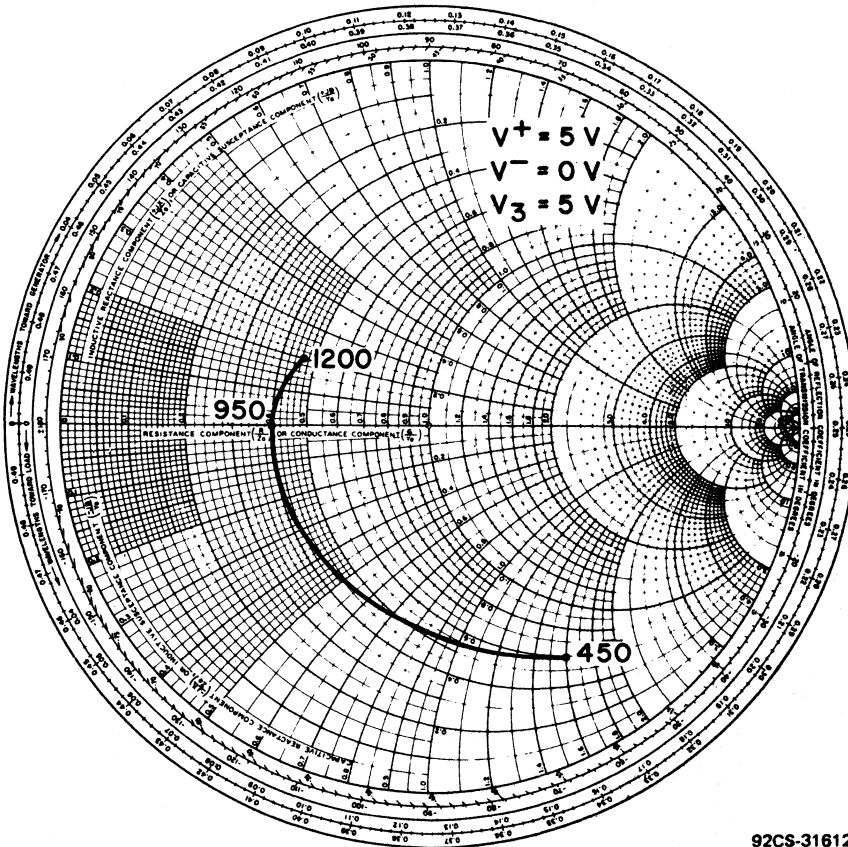


Fig. 17 - Impedance as a function of frequency.

High-frequency construction and design techniques must be followed if the operation of the CA3179G test circuit is to be stable and if the results of repeated tests are to be consistent. The dynamic test circuit is shown in Fig. 4, and a photo of the test fixture that houses it is shown in Fig. 16. Listed below are some precautionary construction considerations for the circuit and test fixture.

1. Supply the ground plane with frequent ground connections.
2. Use 50- Ω coaxial cable for input connections
3. Use a "dead bug" type socket to minimize lead lengths and reduce series inductances
4. Use input pads that reduce impedance mismatch at the generator-test and meter-test input interfaces
5. Use leadless ceramic disc capacitors wherever possible
5. Provide capacitor by-passing near active terminals where ac grounds are required

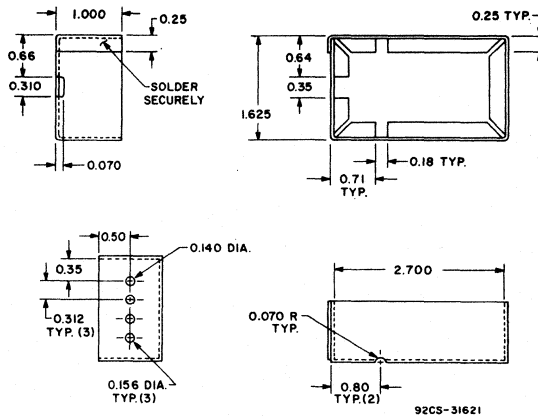
Specific applications may require changes in the procedures listed above. The socket, for instance, can be

eliminated by soldering the device directly to the p.c. board or by using individual board-mounted socket pins. Input and output interface connections and circuitry will also vary according to specific circuit requirements.

Partial Parts List for the Dynamic Test Circuit and Fixture:

- 4 Pasternac PE3493-6 SMA cable connectors and semi-rigid coaxial cable
- 1 Chassis
- 1 P.C. board
- 1 14-lead socket
- 2 1000-pF capacitors, Stettner Trush Inc. No. TEFIC-7
- 3 470-pF disc capacitors
- 3 1000-pF disc capacitors
- 2 33-pF feedthrough capacitors
- 3 1000-pF feedthrough capacitors
- 3 Ferrite beads, 0.375 x 0.187 x 0.250
- 2 Resistors, 390- Ω , 1/4-W, 2%
- 1 Resistor, 56- Ω , 1/8-W, 5%
- 1 Resistor, 110- Ω , 1/8-W, 5%
- 1 Resistor, 9.1- Ω , 1/8-W, 5%
- 1 Resistor, 510- Ω , 1/8-W, 5%

Dimensions of Test Fixture



VHF/UHF \div 4 Prescaler

8-Lead Dual-In-Line
Plastic (Mini-DIP)

H-1817

Features:

- Broadband operation - DC to 1.3 GHz
- High sensitivity
- Standard T^2L or ECL power supply of $5\text{ V} \pm 0.5\text{ V}$
- Complementary ECL outputs

Applications:

- Digital frequency synthesizers for:
VHF/UHF receivers
Satellite communications
Instrumentation

- High-frequency divider for:
UHF frequency counters
UHF timers
High-speed computers
Frequency standards
SHF second IF local-oscillator injection
PCM communications
Satellite communications
Radar ranging systems
- High-frequency up-converters

The CA3199E* is a bipolar integrated fixed-ratio (divide-by-four) counter which operates over the VHF/UHF frequency band (DC to 1.3 GHz). It accepts either single or double-ended ac-coupled input signals and provides complementary emitter follower outputs at standard ECL logic levels.

The CA3199E is supplied in an 8-lead dual-in-line plastic (Mini-DIP) package, and operates over an ambient temperature range of 0 to $+85^\circ\text{C}$.

*Formerly RCA Dev. Type No. TA10853.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE	5.5 V
RMS INPUT VOLTAGE	0.5 V
DEVICE DISSIPATION:	
UP TO $T_A = 70^\circ\text{C}$	630 mW
ABOVE $T_A = 70^\circ\text{C}$	derate linearly at 7.7 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:	
OPERATING	0 to 85°C
STORAGE	-55 to -150°C
LEAD TEMPERATURE (DURING SOLDERING):	
AT DISTANCE $1/16 \pm 1/32$ IN. (1.59 ± 0.79 mm) FROM CASE FOR 10 SECONDS MAX.	-265°C

Linear Integrated Circuits

CA3199E

STATIC CHARACTERISTICS ($T_A=25^\circ\text{C}$, $V_{CC}=+5.0\text{V}$, $V_5=\text{Ground}$)

CHARACTERISTICS	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
"1" Output Voltage, V_{OH}	Outputs Unloaded	—	4.2	—	V
"0" Output Voltage, V_{OL}	Outputs Unloaded	—	3.4	—	V
Internal Bias Voltage, V_{BIAS}	Pin #4 Left Floating	—	2.4	—	V
Power Supply Current Drain, I_D		35	60	85	mA

DYNAMIC CHARACTERISTICS ($T_A=25^\circ\text{C}$, $V_{CC}=+5.0\text{V}$, $V_5=\text{Ground}$)

CHARACTERISTICS	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
Input Frequency Range (sinusoidal), V_{IN}	Single-Ended Input, 1000 MHz	—	—	400	mVpp
Output Voltage Swing, V_6 , V_7		0.6	0.8	—	Vpp
"1" Transition Time, t_{+}	Output Unloaded	—	0.6	—	ns
"0" Transition Time, t_{-}	Output Unloaded	—	0.6	—	ns
Input Capacitance, C_{IN}		—	2.5	—	pF
Input Resistance, R_{IN}		—	400	—	Ω

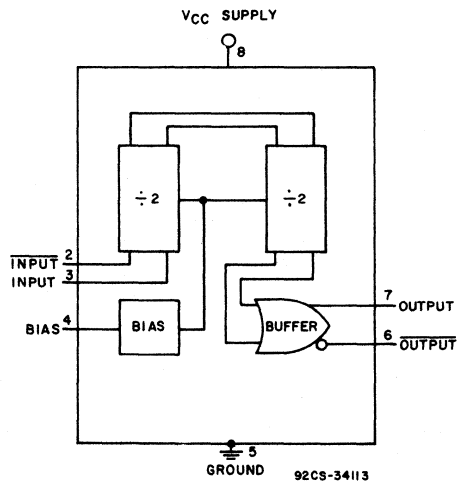


Fig. 1 - Logic diagram for divide-by-four counter.

Special Function Circuits
CA3199E

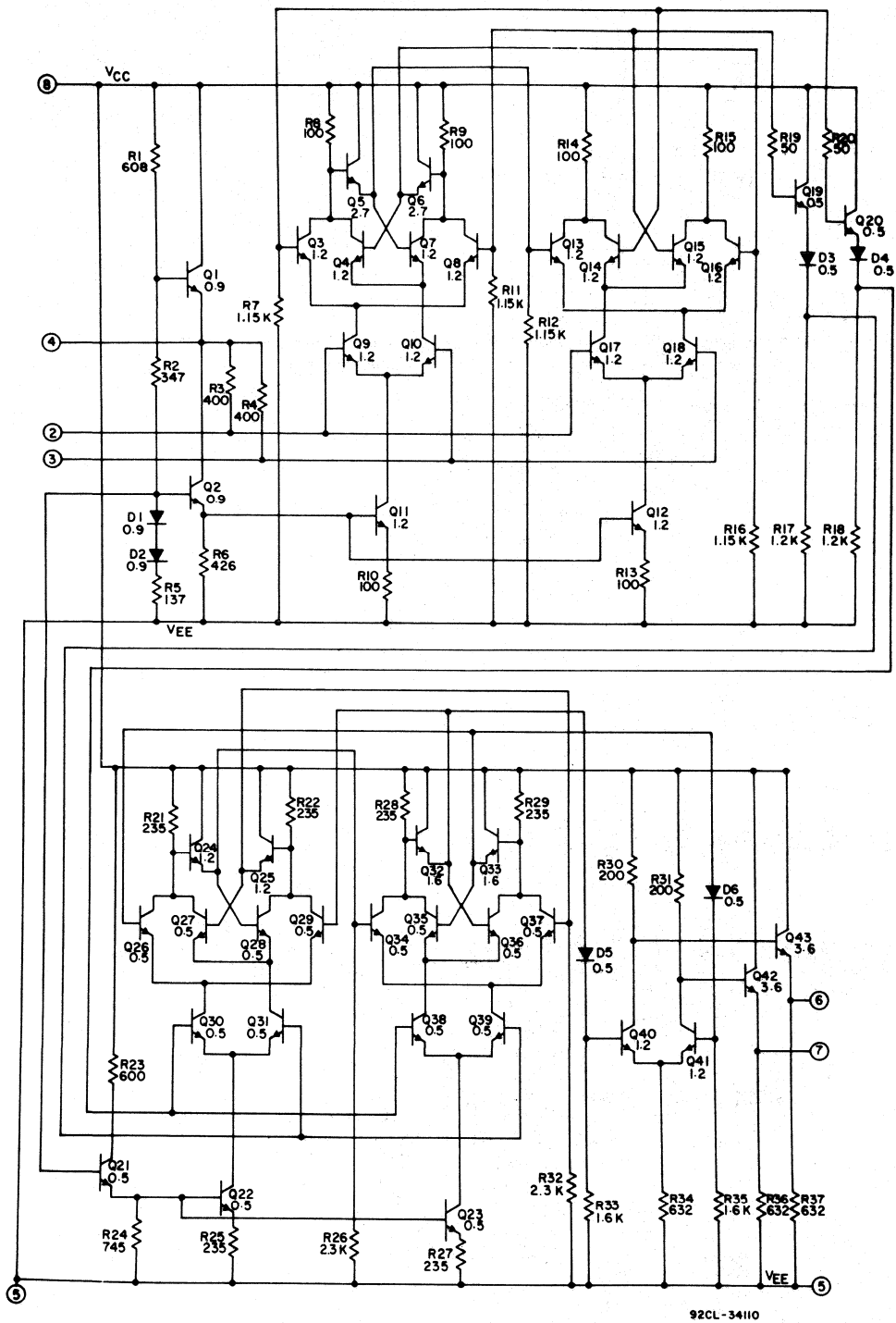


Fig. 6 - Schematic diagram for CA3199E.

Linear Integrated Circuits

CA3199E

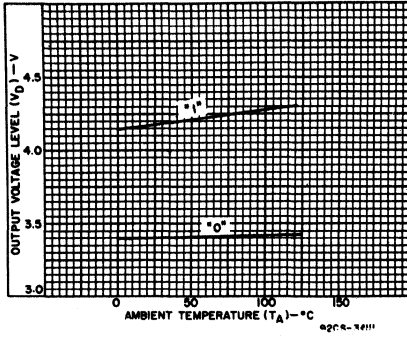


Fig. 2 - Typical output levels as a function of ambient temperature.

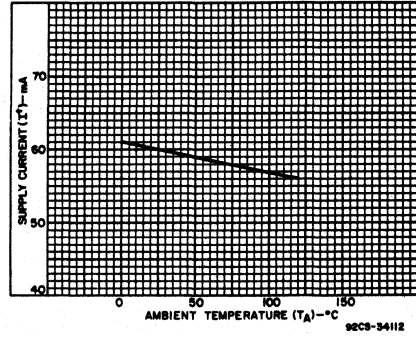


Fig. 3 - Typical power-supply current as a function of ambient temperature.

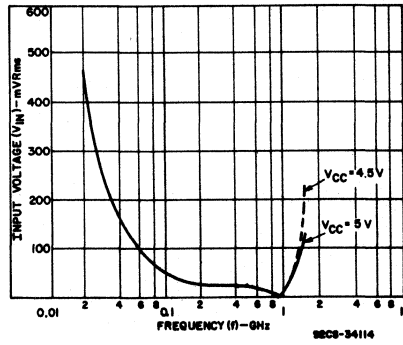
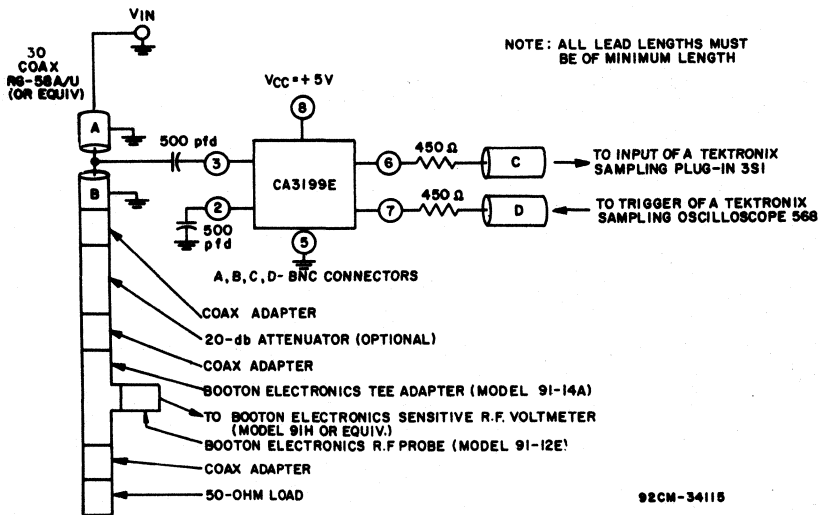
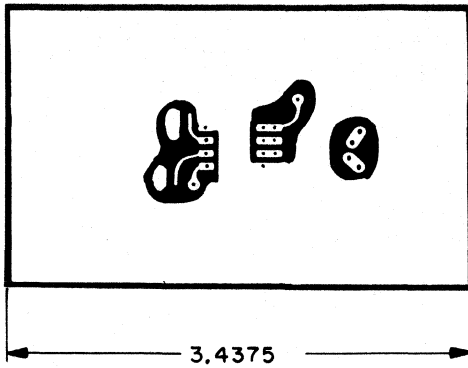


Fig. 4 - Sinusoidal input sensitivity.



92CM-34115

Fig. 5 - Test circuit for CA3199E.



92CS-34146

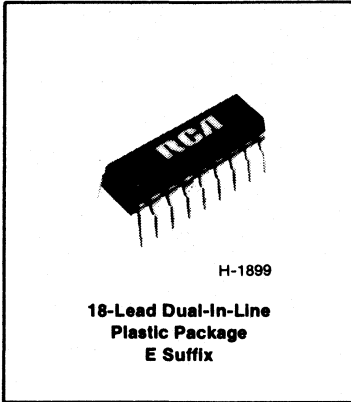
Fig. 7 - Printed-circuit board for the test circuit.

Application and Test Notes

- Both complementary inputs and outputs are provided. When driven single-ended, normally at pin 3, the unused input (pin 2) should be ac by-passed (500 pF) to ground for best performance.
 - Internal bias monitor, pin 4, is normally left floating or ac by-passed to ground.
 - Device inputs should be ac coupled to the signal source. 500-pF coupling capacitors are adequate above 50 MHz.
 - Input signal voltage (sinusoidal) required is 100 mV RMS (typical) over the frequency range of 100-1000 MHz
- When the input signal voltage is a square wave, a rise time of ≤ 5 ns is required. The signal should be 400-800 mV peak-to-peak over the frequency range from dc-1000 MHz. This corresponds to an input slew rate minimum of 62.5 V/ μ s.
 - All test data are for the 8-pin dual-in-line packaged circuit as mounted in a standard IC socket. Somewhat improved higher frequency performance can be obtained by attaching directly to a suitable PC board.
 - High-frequency construction and design techniques must be followed if the operation of the test circuit is to be stable and if the results of repeated tests are to be consistent. Listed below are some precautionary construction considerations for the circuit and test fixture.
 - Supply the ground plane with frequent ground connections.
 - Use 50- Ω coaxial cable for input connections.
 - Use a "dead bug" type socket to minimize lead lengths and reduce series inductances.
 - Use input pads that reduce impedance mismatch at the generator-test and meter-test input interfaces.
 - Use leadless ceramic disc capacitors wherever possible.
 - Provide capacitor by-passing near active terminals where ac grounds are required.

Specific applications may require changes in the procedures listed above. The socket, for instance, can be eliminated by soldering the device directly to the PC board or by using individual board-mounted socket pins. Input and output interface connections and circuitry will also vary according to specific circuit requirements.

CA3211E



VHF/UHF Prescaler

Features

- Divide by 256
- Input frequency to 1 GHz
- Dual input ports electrically selectable
- Input sensitivity <math>< 10 \mu\text{W}</math> typical (Generator available power into a 50- Ω load)
- 5-V power supply
- Balanced output ports

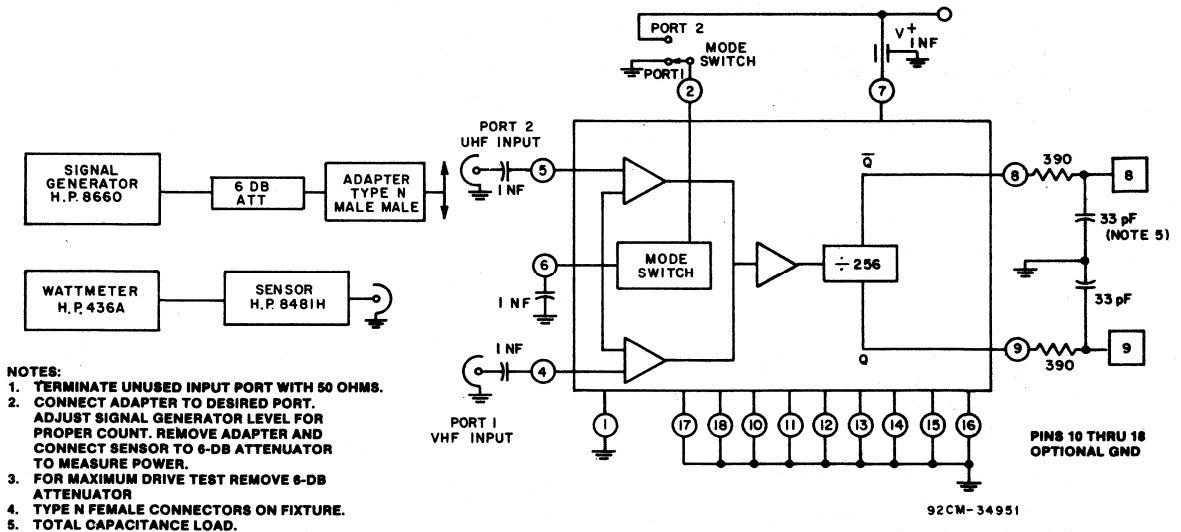
The RCA-CA3211E* is an integrated-circuit prescaler intended for use in TV frequency synthesis tuning systems over an input frequency range of 90 to 1000 MHz. It performs division by 256 in the UHF and VHF mode.

The mode of operation can be selected by means of the bandswitch and the separate UHF and VHF input terminals

provided. The output is a complementary emitter-coupled stage with controlled slew rate for harmonic suppression.

The CA3211E is supplied in a 18-lead dual-in-line plastic package.

*Formerly RCA Developmental No. TA11355.



- NOTES:
1. TERMINATE UNUSED INPUT PORT WITH 50 OHMS.
 2. CONNECT ADAPTER TO DESIRED PORT. ADJUST SIGNAL GENERATOR LEVEL FOR PROPER COUNT. REMOVE ADAPTER AND CONNECT SENSOR TO 6-DB ATTENUATOR TO MEASURE POWER.
 3. FOR MAXIMUM DRIVE TEST REMOVE 6-DB ATTENUATOR
 4. TYPE N FEMALE CONNECTORS ON FIXTURE.
 5. TOTAL CAPACITANCE LOAD.

Fig. 1 - Block diagram and test circuit of the CA3211E.

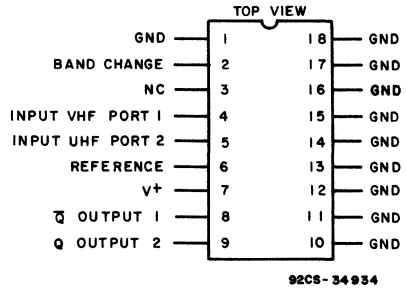
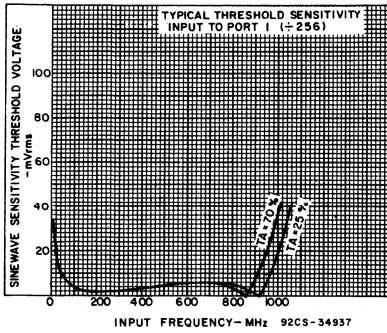
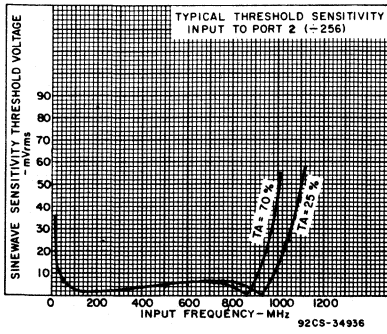
MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE	6 V
DC BANDSWITCH VOLTAGE	20 V
RMS INPUT VOLTAGE	0.5 V
DEVICE DISSIPATION:	
To 70°C	890 mW
Above 70°C	Derate linearly at 11.1 mW/°C
AMBIENT TEMPERATURE:	
Operating	-40 to +85°C
Storage	-65 to +150°C
LEAD TEMPERATURE (During Soldering):	
At distance 1/16 ± 1/32 in. (1.59 mm ± 0.79 mm) from case for 10 s max.	265°C

ELECTRICAL CHARACTERISTICS, T_A=25°C, V₊=5.0 V

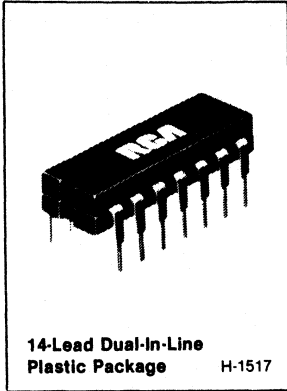
CHARACTERISTIC	LIMITS			UNITS
	Min.	Typ.	Max.	
Supply Current, Terminal 7	30	65	110	mA
Band Change Voltage:				
Port 1 Select (VHF)	-0.5	0	0.6	V
Port 2 Select (UHF)	3	5	18	
Band Change Current, Terminal 2:				
At 0 Volts	—	—	-1	mA
At 18 Volts	—	—	2	
Divide Ratio, f _{IN} ÷ f _{OUT} :				
Port 1, f _{IN} 80-500 MHz	—	256	—	Ratio
Port 2, f _{IN} 80-1000 MHz	—	256	—	
Input Sensitivity, f _{IN} :				
40 MHz	—	15	—	mV rms
80 MHz	—	10	35	
150-800 MHz	—	10	20	
900 MHz	—	10	35	
1000 MHz	—	15	45	
Maximum Drive Level:				
80-1000 MHz	500	—	—	mV rms
Output at Terminal 9 or 8:				
Mean Value	—	3.5	—	V dc
Peak-Peak Swing	0.75	1	—	V _{p-p}
Rise or Fall Time	—	70	—	ns
Internal Bias at Terminal 6	—	2	—	V dc
Internal Bias, Terminal 2=5 V:				
At Terminal 4	—	0.07	—	V dc
At Terminal 5	—	2	—	

CA3211E



TERMINAL DIAGRAM

Fig. 2 - Sinewave sensitivity threshold voltage as a function of input frequency.



BiMOS Single-Chip Detector/Alarm System

With Integral Drivers for Mechanical and
Piezoelectric Horn Alarms

Features:

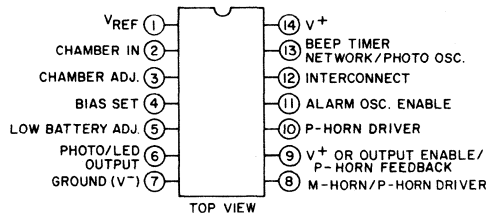
- Interfaces directly with high Z sensors — no external buffer FET required
- Low input current: 1 pA max.
- Gate-protected input terminals
- On-chip beep oscillator for low battery indication
- Self-contained low-battery-voltage detection circuit
 - (a) Fixed or adjustable trip point available
 - (b) Dynamic battery test when filter capacitor = 2 μ F

The RCA-CA3164E is a monolithic BiMOS integrated circuit designed to meet the stringent system requirements of a battery- or line-operated alarm circuit. When used with an ionization chamber and electromechanical or piezoelectric horn, it provides a one-chip approach to smoke detection. No external active devices are required to interface with either the chamber input or horn output terminals. The CA3164E can also be used with photoelectric chambers by the addition of several external components.

The CA3164E is supplied in the 14-lead dual-in-line plastic package.

- Chamber trigger voltage independent of battery supply voltage (less than 150 mV over temperature and supply variations)
- Reference source current available = 5 μ A (typ.)
- Low standby battery current = 8 μ A (typ.)
- Can be used with photoelectric sensors by using a minimum of external passive components in combination with the RCA-CA3078 micropower op-amp
- Multiple-unit interconnect terminal controls a common annunciator circuit
 - (a) A fault to ground doesn't prevent local operation
 - (b) The low battery alarm signal triggers only the local unit
- LED output indicates status of smoke-detector circuit
- Operates from 11 V (max.) supply (either battery or line)
- Battery reversal protection feature

TERMINAL ASSIGNMENT



92CS-31019R1

Linear Integrated Circuits

CA3164E

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE, V^+	+ 11 V
DEVICE DISSIPATION, P_D :	
Up to $T_A = 25^\circ\text{C}$600 mW
Above $T_A = 25^\circ\text{C}$ derate linearly at6.7 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:	
Operating	0 to + 50 $^\circ\text{C}$
Storage	- 65 to + 150 $^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 ± 1/32 inch (1.59 ± 0.79 mm) from case for 10 seconds max.	+ 265 $^\circ\text{C}$

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V^+ = 9\text{ V}$

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
Operating Voltage		7	9	11	V
Common-Mode Input Voltage Range, VICR	$(V^+ - 2\text{ V}) = 7\text{ V}$	0	—	7	V
Low-Battery Trigger Voltage	External adjust (increase only)	7.3	7.7	7.9	V
Horn Driver $V_{CE}(\text{sat})$	Term. 8 = 100 mA	—	—	0.5	V
	Term. 8 = 300 mA	—	—	1.1	
Reference Voltage	Term. 1	6.1	6.5	6.9	V
Input Leakage Current, I_L	Term. 2	—	—	1	pA
	Term. 2 at 50 $^\circ\text{C}$	—	—	2.5	
	Term. 3	—	—	50	
Standby Current (10 M Ω from Term. 4 to gnd)	No LED connected	—	8*	14	μA
	LED connected - 20 mA for 30 ms every 60 s	—	18	—	
	Photoelectric operation - LED photocurrent = 0.6 A (5-second rate)	—	13	—	
Reference Source Current		5	—	—	μA
LED Driver Sink Current	Term. 6	20	50	—	mA
Output Sink Current	Term. 8 = 1.1 V	200	300	—	mA
	Term. 8 = 0.5 V	100	150	—	
	Term. 10 = 2 V	20	25	—	
Output Source Current	Term. 8 = $V^+ - 2\text{ V}$	20	25	—	mA
	Term. 10 = $V^+ - 2\text{ V}$	20	25	—	
Interconnect Current	$V_O = 0\text{ V}$	1.5	3.5	6	mA
	$V_O = 9\text{ V}$	—	45	65	μA
Remote Fan-Out		20	—	—	
Low-Battery Adjust, Term.5 Input Current		50	70	225	nA
Timing Current	Term. 13	10	—	62	nA
LED Blink Period	Adjustable	—	—	1	PPM
LED Pulse Width	Fixed	—	30	—	ms
Alarm Pulse Duty Cycle (4.7 M Ω from Term. 11 to gnd)	On-time	—	95	—	%
	On-time = 95%	—	0.5	—	sec.
	Off-time = 5%	—	0.026	—	

*Adjustable to 5 μA .

OPERATING MODE TRUTH TABLE

CONDITION	BATTERY	LED TERM. 6	ALARM HORN TERMS. 8, 9, 10	SYSTEM REMOTE OUTPUT TERM. 12	REMOTE UNIT ALARM STATUS
No Smoke In Chamber	NORMAL	BLINK ¹	OFF	LOW	OFF
No Smoke In Chamber	LOW	BLINK ¹	BEEP ¹	LOW	OFF
Smoke In Chamber	X	ON ²	ON ²	HIGH	ON
Remote Alarm On, No Smoke In Local Chamber	X	BLINK ¹	ON ²	HIGH ³	ON

X = Don't Care

- 30-ms pulse every 50 seconds (typ.).
- Alarm horn may be programmed for continuous sound by connecting terminal 11 to V⁺. The alarm may be pulsed by connecting terminal 11 to ground through a resistor (from 3.9 to 10 MΩ). The typical duty cycle is 95% ON, and is determined by the size of the resistor.
- Signal received from activated remote alarm.

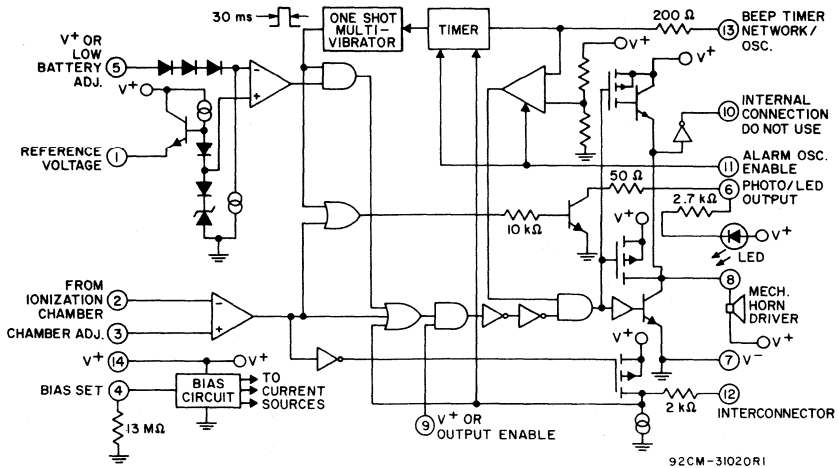


Fig. 1 - Simplified functional diagram for CA3164E.

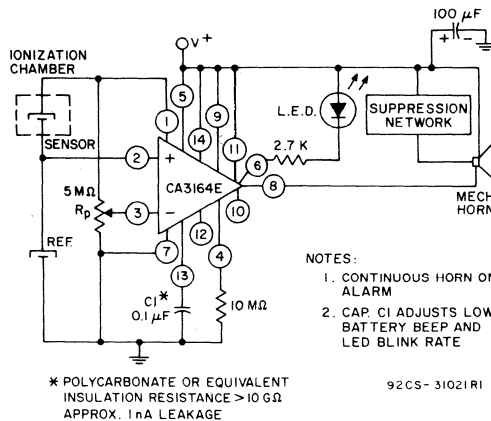


Fig. 2 - Basic ionization detector with electromechanical horn.

CA3164E

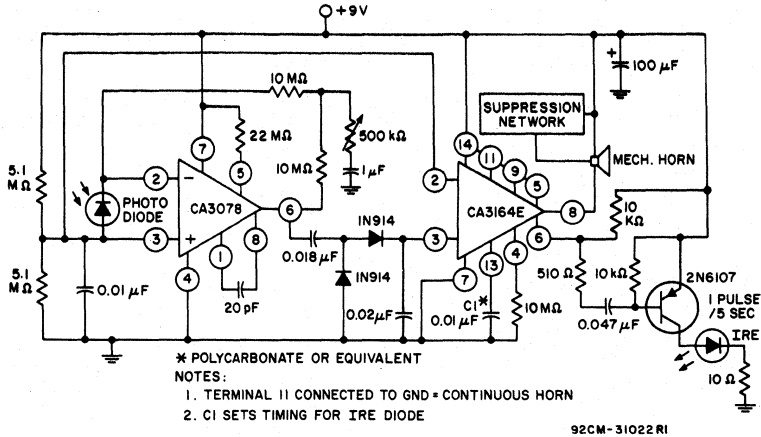


Fig. 3 - Typical photoelectric system using CA3164E.

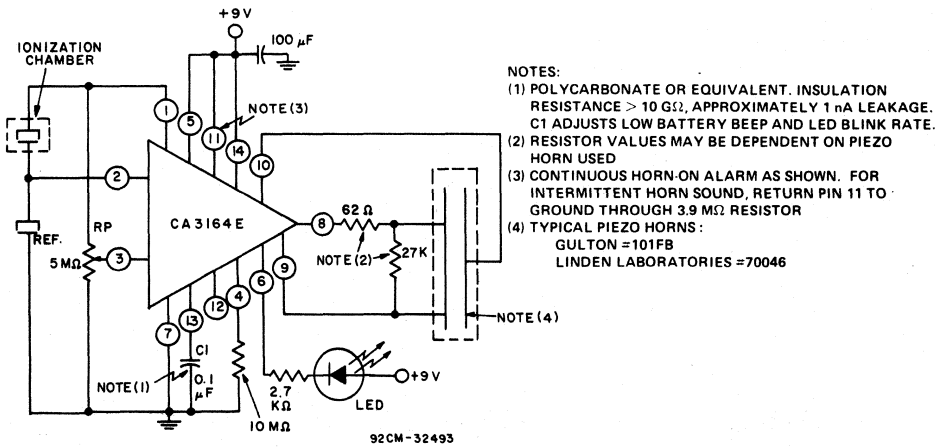
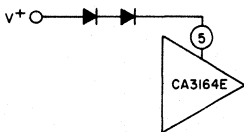


Fig. 4 - Basic ionization detector with piezoelectric horn.

Connections for Optional Functions

- Low Battery Adjustment - Terminal 5**
 Add diodes as shown below to increase the low-battery trigger point.



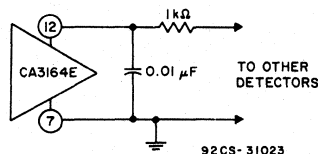
- Sounder Operating Mode**

Continuous sound on alarm - connect terminal 11 to V+.

Pulsed sound on alarm - connect a 3.9-MΩ resistor between terminal 11 and ground.

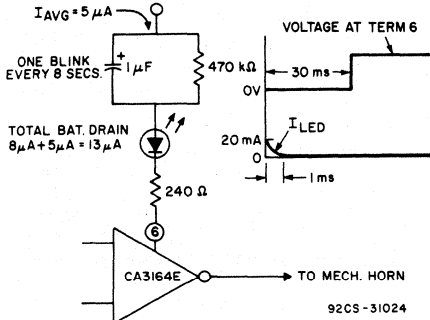
- Remote (Interconnect)**

Connect terminal 12 to same terminal on all other units (fan out = 20 units). When interconnecting units for the remote-alarm function, the extremely low currents involved make it extremely important that a provision be made for limiting externally induced transients into the remote terminal. For example, inadvertent contact with external power sources or electrical storm activity may cause triggering of the remote alarm function. The circuit below will reduce the possibility of such occurrences.



4. LED On-Time Adjustment

The CA3164E is designed to provide a fixed LED on-time of approximately 30 ms. For applications requiring a reduction in on-time, the following circuit is recommended:



This circuit reduces the LED on-time but does not affect the horn on-time of 30 ms. When using this configuration during the continuous-alarm mode (smoke in chamber), the LED will be off instead of on, as shown in the truth table. If the horn is pulsed during the alarm mode, the LED will blink at the pulse rate.

Cleaning Procedure

To insure leakage currents of less than 1 pA, the following procedure is recommended:

- (a) degrease in trichlorethylene
- (b) rinse in de-ionized water

Circuit Description

Basic Functions - The CA3164E is designed to interface directly with an ionization-chamber type of smoke detector. Upon being triggered by a decreasing voltage at the ionization-chamber output, the IC operates a mechanical transducer. In addition to this basic smoke-detector function, another circuit monitors and compares the battery voltage to an internal reference-voltage source. Once the battery voltage drops below a defined level, a short 30-ms beep sound is produced in synchronism with an LED indicator every 50 seconds. This rate is determined by a programming resistor connected between terminal 4 and ground and an external 0.1-μF capacitor connected between terminal 13 and ground.

A buffered output voltage is available from the reference supply that may be used to operate the ionization chamber. This voltage helps maintain constant sensitivity with decreasing supply voltage.

There are two alarm modes and two conditions that will sound the alarm. The first alarm condition is the normal smoke in the ionization chamber; the other condition is a high level to the remote input/output terminal of the IC.

The first alarm mode is the customary continuous sound. The second alarm mode is an interrupted or pulsed sound.

Operation - The CA3164E is current programmable by placing a resistor from terminal 4 to ground. This resistor establishes the operating current levels for all the current sources within the IC including the timing circuits.

An operational amplifier configuration is used for the ionization chamber input. P-channel MOS field-effect transistors are used on this input in the bootstrap configuration shown in Fig. 5 to drive the protection diodes and maintain the sub-picoampere input current.

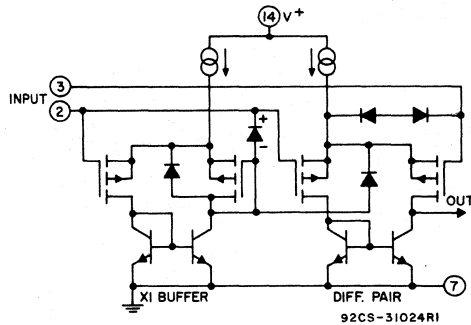


Fig. 5 - Schematic of ionization-chamber amplifier.

A conventional bipolar amplifier is used for the battery monitor circuit. The zener diode is biased at about 3 μA. This zener voltage is raised one V_{AK} and then applied to the base of an emitter-follower transistor to buffer and reflect the zener voltage to the outside reference terminal. By providing an additional input terminal (terminal 5), where three level-shifting diodes are available, an additional external means is provided to raise the voltage level at which the CA3164E goes into the low-voltage alarm mode.

An integrating type of timer is used to generate the one-minute LED power-monitor and battery-function indicator pulse. Fig. 6 shows the system. A constant-current source charges the external 0.1-μF timing capacitor C_T , which subsequently triggers the 30-ms one-shot multivibrator composed of n-channel MOS transistor N_3 and n-p-n transistor Q_1 .

N_3 is then cut off and its drain climbs to the supply rail, linearly charging capacitor C_{PULSE} . When the drain of N_3 reaches the supply rail, the charging current ceases, cutting off the base current of Q_1 and discharging the capacitor.

A open-collector n-p-n transistor is used to drive the optional external LED power monitor and battery-condition indicator (Fig. 1).

CA3164E

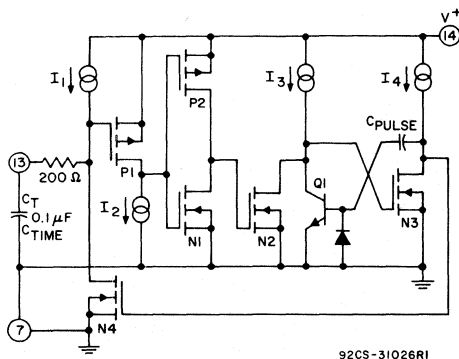


Fig. 6 - Schematic of timer and one-shot multivibrator.

The schematic diagram of the drive circuit for a mechanical horn (M-horn) and a piezoelectric horn (P-horn) is shown in Fig. 7. For M-horn operation, the output of the driver at terminal 8 is used. A large n-p-n transistor Q3 with an active pull-up transistor Q2 provide over 300 mA of drive current. In the M-horn mode, terminal 9 must be returned directly to V^+ . P-horn operation requires the output from a second inverting amplifier at terminal 10, as well as the output from terminal 8. For P-horn operation, terminal 9 is connected to the feedback terminal of the horn.

The horn output, on alarm, can be continuous or pulsed. The mode is determined by the connection of terminal 11. When this terminal is connected to V^+ , the alarm sound is continuous, and when it is connected to ground through a programming resistor, as shown in Fig. 7, the alarm is pulsed. The pulse rate is determined by the sum of the current through

the programming resistor connected to terminal 11 and the current from the basic timer-current source. Thus, when the detector goes into the alarm mode, the nominal 50-second time period is decreased to a nominal 0.5-second period. This 0.5-second period is set by the external 3.9-M Ω resistor. PMOS transistor P4 and bipolar transistor Q6 provide the on-off switching of NMOS transistor N4 in the driver circuit to provide the pulsed output from the horn.

Terminal 12, the interconnect terminal, is both an input and output for the circuit. When connected by two wires to other units, alarm in any one unit will activate the other units. A small sinking current of only 10 μ A keeps the line impedance down while a sourcing current of over 2 mA is available in the alarm mode. This current is more than sufficient to trigger over 20 additional units.

Other Applications of the CA3164E

Although the primary function of the CA3164E is smoke detection, it may also be used in many other circuits that require high front-end sensitivity and the very high input resistance of MOS transistors. The internal circuitry of the CA3164E requires a minimum of external components, and the low battery drain eliminates the need for ac power in most circuits.

A few of the possible uses are: humidity sensor, where two metal electrodes replace the ionization chamber; intrusion alarm; P-horn driver; controller for a dc-to-dc converter such as might be used in an electronic photoflash unit; or with a photodiode as an automatic switch for turning on night lights.

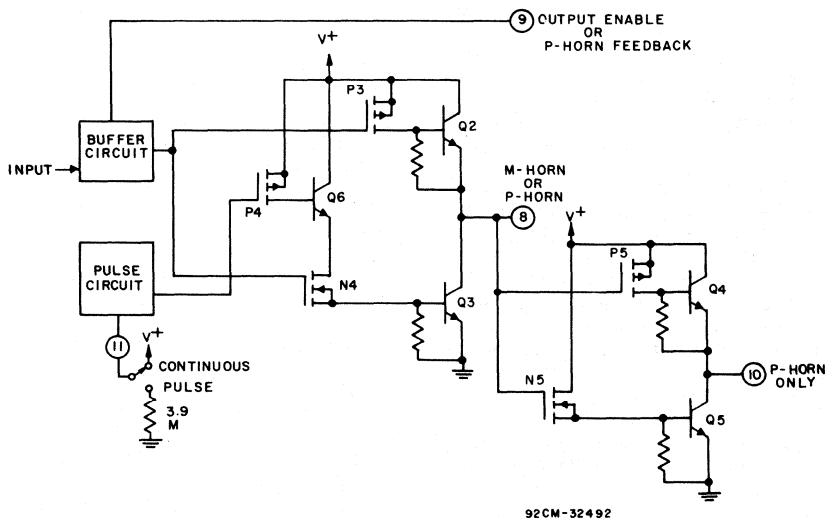
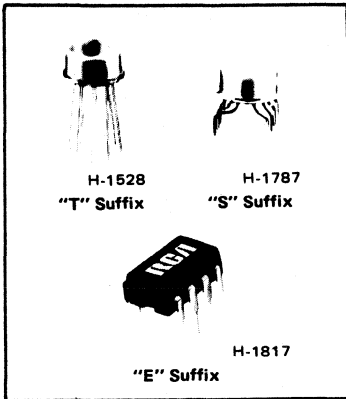


Fig. 7 - Schematic of mechanical and piezoelectric horn drivers.



Timers

For Timing Delays & Oscillator Applications in Commercial, Industrial, and Military Equipment

CA555T, CA555CT: Standard 8-Lead TO-5 Style Package
CA555S, CA555CS: Standard 8-Lead TO-5 Style Package With Formed Leads (DIL-CAN)
CA555E, CA555CE: 8-Lead Dual-In-Line Plastic Package (MINI-DIP)

Features:

- Accurate timing from microseconds through hours
- Astable and monostable operation
- Adjustable duty cycle
- Output capable of sourcing or sinking up to 200 mA
- Output capable of driving TTL devices
- Normally ON and OFF outputs
- High-temperature stability - 0.005%/°C

- Directly interchangeable with SE555, NE555, MC1555, and MC1455

Applications

- Precision timing
- Sequential timing
- Time-delay generation
- Pulse generation
- Pulse-width and position modulation
- Pulse detector

The RCA-CA555 and CA555C are highly stable timers for use in precision timing and oscillator applications. As timers, these monolithic integrated circuits are capable of producing accurate time delays for periods ranging from microseconds through hours. These devices are also useful for astable oscillator operation and can maintain an accurately controlled free-running frequency and duty cycle with only two external resistors and one capacitor.

The circuits of the CA555 and CA555C may be triggered by the falling edge of the wave-form signal, and the output of these circuits can source or sink up to a 200-milliampere current or drive TTL circuits.

The CA555 and CA555C are supplied in standard 8-lead TO-5 style packages (T suffix), 8-lead TO-5 style packages with dual-in-line formed leads (DIL-CAN, S suffix), 8-lead dual-in-line plastic packages (MINI-DIP, E suffix), and in chip form (H suffix). These types are direct replacement for industry types in packages with similar terminal arrangements e.g. SE555 and NE555, MC1555 and MC1455, respectively. The CA555 type circuits are intended for applications requiring premium electrical performance. The CA555C type circuits are intended for applications requiring less stringent electrical characteristics.

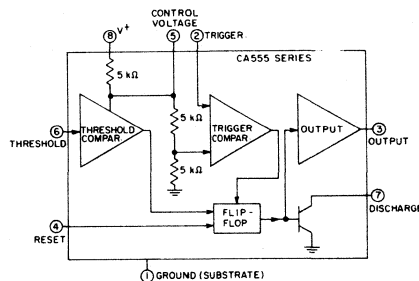


Fig. 1 — Functional diagram of the CA555 series.

Linear Integrated Circuits

CA555, CA555C Types

ELECTRICAL CHARACTERISTICS, At $T_A = 25^\circ\text{C}$, $V^+ = 5$ to 15 V unless otherwise specified

CHARACTERISTIC	TEST CONDITIONS	LIMITS						UNITS
		CA555			CA555C			
		Min.	Typ.	Max.	Min.	Typ.	Max.	
DC Supply Voltage, V^+		4.5	—	18	4.5	—	16	V
DC Supply Current (Low State)*, I^+	$V^+ = 5$ V, $R_L = \infty$	—	3	5	—	3	6	mA
	$V^+ = 15$ V, $R_L = \infty$	—	10	12	—	10	15	mA
Threshold Voltage, V_{TH}		—	$(2/3)V^+$	—	—	$(2/3)V^+$	—	V
Trigger Voltage	$V^+ = 5$ V	1.45	1.67	1.9	—	1.67	—	V
	$V^+ = 15$ V	4.8	5	5.2	—	5	—	V
Trigger Current		—	0.5	—	—	0.5	—	μA
Threshold Current Δ , I_{TH}		—	0.1	0.25	—	0.1	0.25	μA
Reset Voltage		0.4	0.7	1.0	0.4	0.7	1.0	V
Reset Current		—	0.1	—	—	0.1	—	mA
Control Voltage Level	$V^+ = 5$ V	2.9	3.33	3.8	2.6	3.33	4	V
	$V^+ = 15$ V	9.6	10	10.4	9	10	11	V
Output Voltage Drop: Low State, V_{OL}	$V^+ = 5$ V $I_{SINK} = 5$ mA	—	—	—	—	0.25	0.35	V
	$I_{SINK} = 8$ mA	—	0.1	0.25	—	—	—	V
	$V^+ = 15$ V $I_{SINK} = 10$ mA	—	0.1	0.15	—	0.1	0.25	V
	$I_{SINK} = 50$ mA	—	0.4	0.5	—	0.4	0.75	V
	$I_{SINK} = 100$ mA	—	2.0	2.2	—	2.0	2.5	V
	$I_{SINK} = 200$ mA	—	2.5	—	—	2.5	—	V
High State, V_{OH}	$V^+ = 5$ V $I_{SOURCE} = 100$ mA	3.0	3.3	—	2.75	3.3	—	V
	$V^+ = 15$ V $I_{SOURCE} = 100$ mA	13.0	13.3	—	12.75	13.3	—	V
	$I_{SOURCE} = 200$ mA	—	12.5	—	—	12.5	—	V
Timing Error (Monostable): Initial Accuracy	$R_1, R_2 = 1$ to 100 k Ω	—	0.5	2	—	1	—	%
Frequency Drift with Temperature	$C = 0.1$ μF Tested at $V^+ = 5$ V,	—	30	100	—	50	—	p/m/ $^\circ\text{C}$
Drift with Supply Voltage	$V^+ = 15$ V	—	0.05	0.2	—	0.1	—	%/V
Output Rise Time, t_r		—	100	—	—	100	—	ns
Output Fall Time, t_f		—	100	—	—	100	—	ns

* When the output is in a high state, the dc supply current is typically 1 mA less than the low-state value.

Δ The threshold current will determine the sum of the values of R_1 and R_2 to be used in Fig. 16 (astable operation): the maximum total $R_1 + R_2 = 20$ M Ω .

Special Function Circuits CA555, CA555C Types

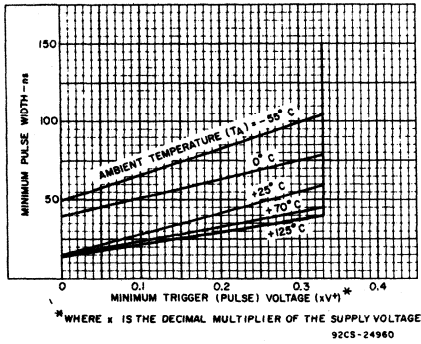


Fig.2 - Minimum pulse width vs. minimum trigger voltage.

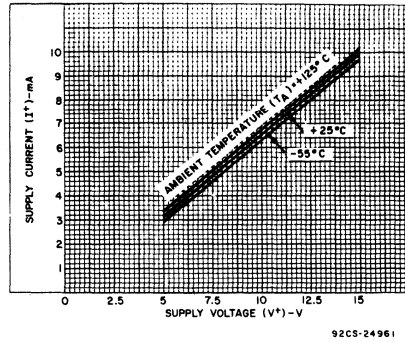


Fig.3 - Supply current vs. supply voltage.

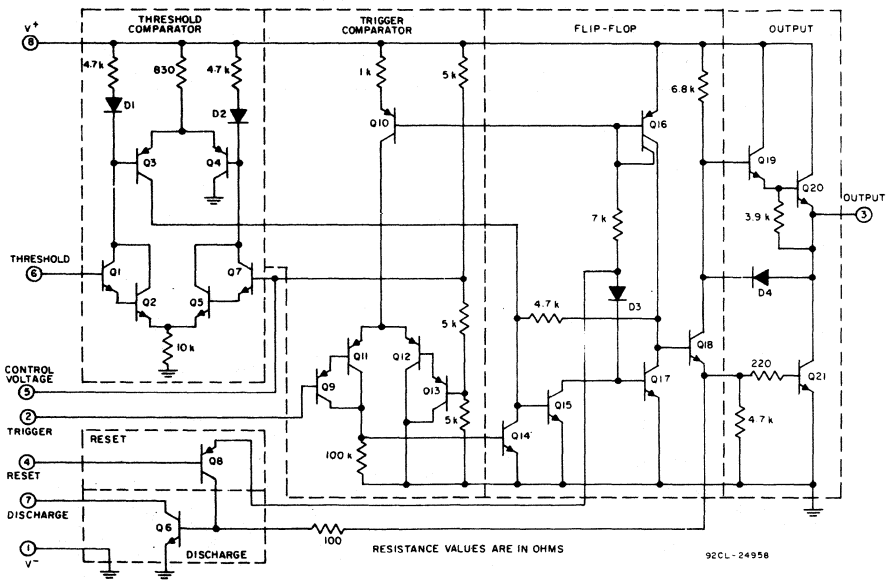
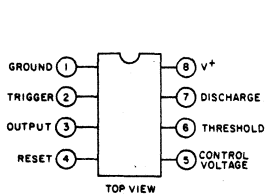
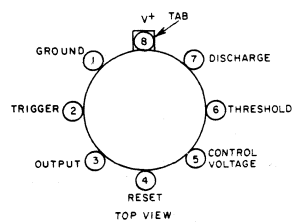


Fig.4 - Schematic diagram of the CA555 and CA555C.



a. MINI-DIP plastic package
TO-5 style package with formed leads



b. TO-5 style package

Fig.5 - Terminal assignment diagrams.

Linear Integrated Circuits

CA555, CA555C Types

MAXIMUM RATINGS, Absolute-Maximum Values:
 DC SUPPLY VOLTAGE 18 V
 DEVICE DISSIPATION:
 Up to $T_A = 55^\circ\text{C}$ 600 mW
 Above $T_A = 55^\circ\text{C}$ Derate linearly 5 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE (All Types):
 Operating -55 to $+125$ $^\circ\text{C}$
 Storage -65 to $+150$ $^\circ\text{C}$
LEAD TEMPERATURE (During Soldering):
 At distance $1/16'' \pm 1/32''$
 (1.59 ± 0.79 mm) from case
 for 10 seconds max. $+265$ $^\circ\text{C}$

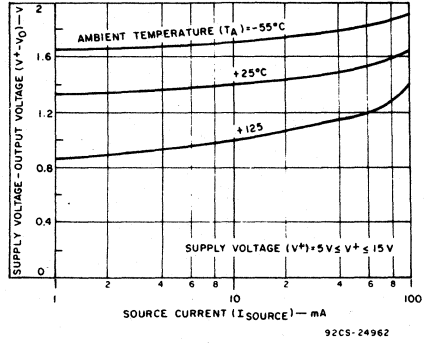


Fig. 6 - Output voltage drop (high state) vs. source current.

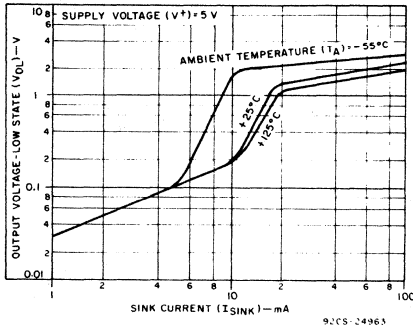


Fig. 7 - Output voltage-low state vs. sink current at $V^+ = 5$ V.

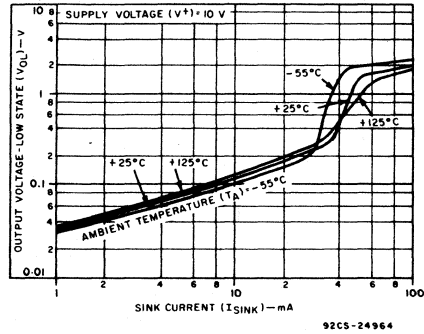


Fig. 8 - Output voltage-low state vs. sink current at $V^+ = 10$ V.

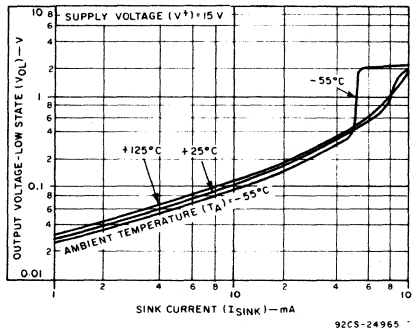


Fig. 9 - Output voltage-low state vs. sink current at $V^+ = 15$ V.

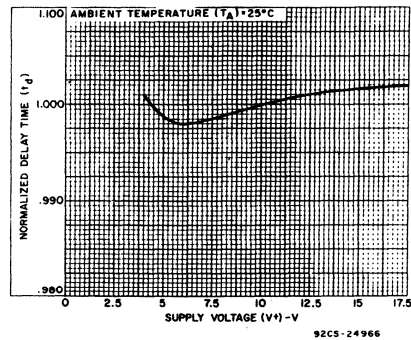


Fig. 10 - Delay time vs. supply voltage.

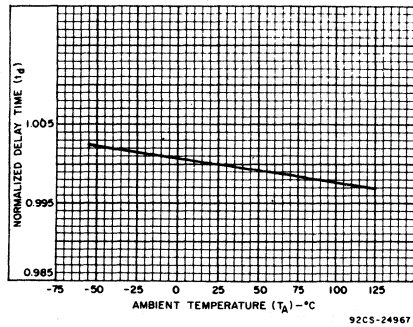


Fig. 11 - Delay time vs. temperature.

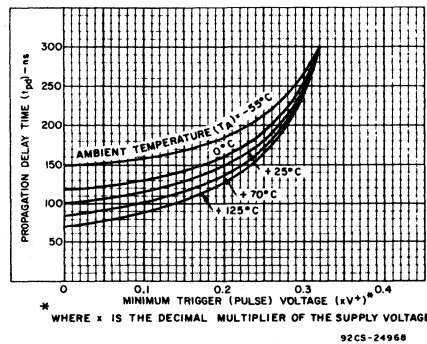


Fig. 12 - Propagation delay time vs. trigger voltage.

TYPICAL APPLICATIONS

Reset Timer (Monostable Operation)

Fig. 13 shows the CA555 connected as a reset timer. In this mode of operation capacitor C_T is initially held discharged by a transistor on the integrated circuit. Upon closing the "start" switch, or applying a negative trigger pulse to terminal 2, the integral timer flip-flop is "set" and releases the short circuit across C_T which drives the output voltage "high" (relay energized). The action allows the voltage across the capacitor to increase exponentially with the time constant $t = R_1 C_T$. When the voltage across the capacitor equals $2/3 V^+$, the comparator resets the flip-flop which in turn discharges the capacitor rapidly and drives the output to its low state.

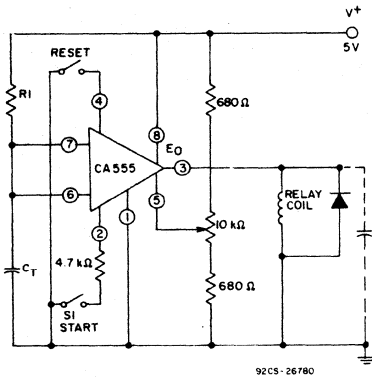


Fig. 13 – Reset timer (monostable operation).

Since the charge rate and threshold level of the comparator are both directly proportional to V^+ , the timing interval is relatively independent of supply voltage variations. Typically, the timing varies only 0.05% for a 1 volt change in V^+ .

Applying a negative pulse simultaneously to the reset terminal (4) and the trigger terminal (2) during the timing cycle discharges C_T and causes the timing cycle to restart. Momentarily closing only the reset switch during the timing interval discharges C_T , but the timing cycle does not restart.

Fig. 14 shows the typical waveforms generated during this mode of operation, and Fig. 15 gives the family of time delay curves with variations in R_1 and C_T .

Repeat Cycle Timer (Astable Operation)

Fig. 16 shows the CA555 connected as a repeat cycle timer. In this mode of operation, the total period is a function of both R_1 and R_2 ;

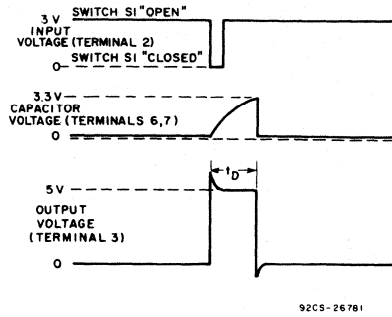


Fig. 14 – Typical waveforms for reset timer.

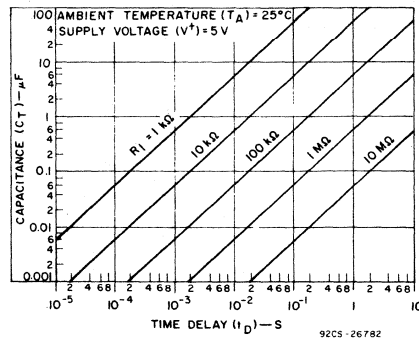


Fig. 15 – Time delay vs. resistance and capacitance.

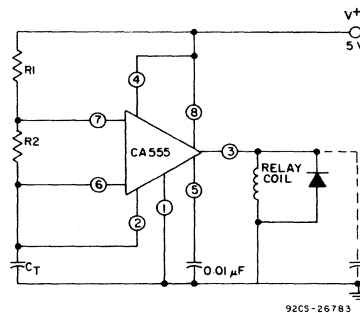


Fig. 16 – Repeat cycle timer (astable operation).

$$T = 0.693(R_1 + 2R_2)C_T = t_1 + t_2$$

where $t_1 = 0.693(R_1 + R_2)C_T$

and $t_2 = 0.693(R_2)C_T$

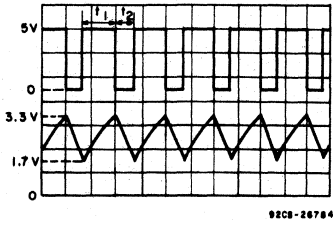
The duty cycle is:

$$\frac{t_2}{t_1 + t_2} = \frac{R_2}{R_1 + 2R_2}$$

Typical waveforms generated during this mode of operation are shown in Fig. 17. Fig. 18 gives the family of curves of free running frequency with variations in the value of $(R_1 + 2R_2)$ and C_T .

Linear Integrated Circuits

CA555, CA555C Types



Top Trace: Output voltage (2V/div. and 0.5 ms/div.)
 Bottom Trace: Capacitor voltage (1 V/div. and 0.5 ms/div.)

Fig.17 — Typical waveforms for repeat cycle timer.

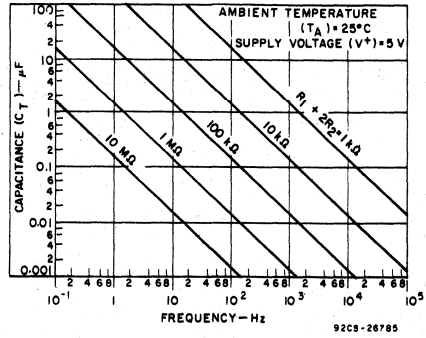


Fig.18 — Free running frequency of repeat cycle timer with variation in capacitance and resistance.

TV/CATV Circuits

Technical Data

AFT	Page
CA3064.....	660
CA3139.....	668

Chroma Systems

CA1398.....	673
CA3070.....	678
CA3071.....	678
CA3072.....	678
CA3121.....	693
CA3125.....	699
CA3126.....	702
** CA3128.....	471
CA3137.....	709
CA3145.....	714
CA3151.....	721
CA3158.....	725
CA3170.....	731
CA3172.....	737
** CA3194.....	740
CA3201.....	749
CA3217.....	756
CA3221.....	765

Horizontal Systems

CA920A.....	771
CA1391.....	775
CA1394.....	775
CA3154.....	780
CA3157.....	786
CA3159.....	792
*** CA3190.....	796
CA3202.....	802
CA3210.....	809
*** CA3223.....	809

- * BIMOS type
- ** PAL
- *** 625 Line
- Δ CMOS types

Sync/AGC	Page
CA3120.....	819
CA3142.....	819

Luminance Processors

CA3135.....	827
CA3143.....	834
CA3144.....	839
CA3156.....	844

Multiplex Decoders

CA758.....	849
CA1310A.....	855
CA3090A.....	860
CA3195.....	866

PIX IF

CA270.....	871
CA1352.....	876
CA3068.....	880
CA3136.....	887
CA3153.....	892
CA3191.....	899
CA3192.....	912
CA7607.....	920
CA7611.....	920

Remote Control

CA3035.....	See Page 362
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Sound IF	Page
CA1190.....	924
CA1191.....	928
CA2111A.....	932
CA2136A.....	937
CA3011.....	939
CA3012.....	939
CA3013.....	945
CA3014.....	945
CA3041.....	952
CA3042.....	960
CA3065.....	968
CA3134.....	974

Tuning

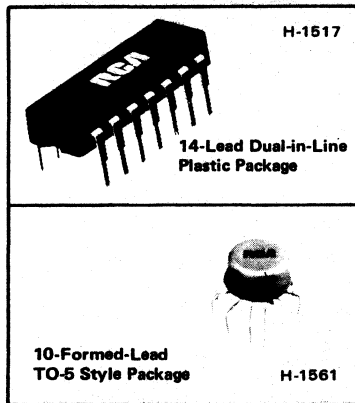
CA3140.....	See Page 156
CA3152*.....	See Page 48
CA3163.....	980
CA3166.....	984
CA3168.....	See Page 339
CA3199.....	See Page 639
CA3211.....	See Page 644

Video Disc Circuits

CA2111A.....	932
CA3215.....	990
CA3216.....	993
Δ CD3226.....	997

Linear Integrated Circuits

CA3064, CA3064E



TV Automatic Fine Tuning Circuit

Features:

- Cascode type high-gain amplifier (18 mV input for rated output)
- Internal voltage regulator
- Differential detector
- For use with either color or monochrome
- Differential amplifier
- Bipolar outputs
- Wide operating-temperature range; -55 to $+125^{\circ}\text{C}$

RCA-CA3064 and CA3064E represent the third generation of integrated circuits designed primarily for AFC (Automatic-Frequency-Control) applications. They provide all of the signal-processing components needed (with the exception of the tuned-phase-detector transformer) to derive the AFT correction signals from the output of the video-if amplifier. The CA3064 is supplied in the 10-formed-lead TO-5 style package, and the CA3064E in the 14-lead dual-in-line plastic package. Both types operate over the temperature range of -55 to $+125^{\circ}\text{C}$.

The CA3064 and CA3064E are functionally similar to the CA3044 and CA3044V1 but embody a higher-gain input amplifier which provides a 20-dB improvement in sensitivity. The increased sensitivity extends the application of a proven AFT system to the low-level if-amplifier stages in TV receivers.

Because the CA3064 and CA3064E are functionally similar to the CA3044 and CA3044V1, refer to Application Note ICAN-5831, "Application of the RCA CA3044 and CA3044V1 Integrated Circuits in Automatic Fine-Tuning Systems" for general application information.

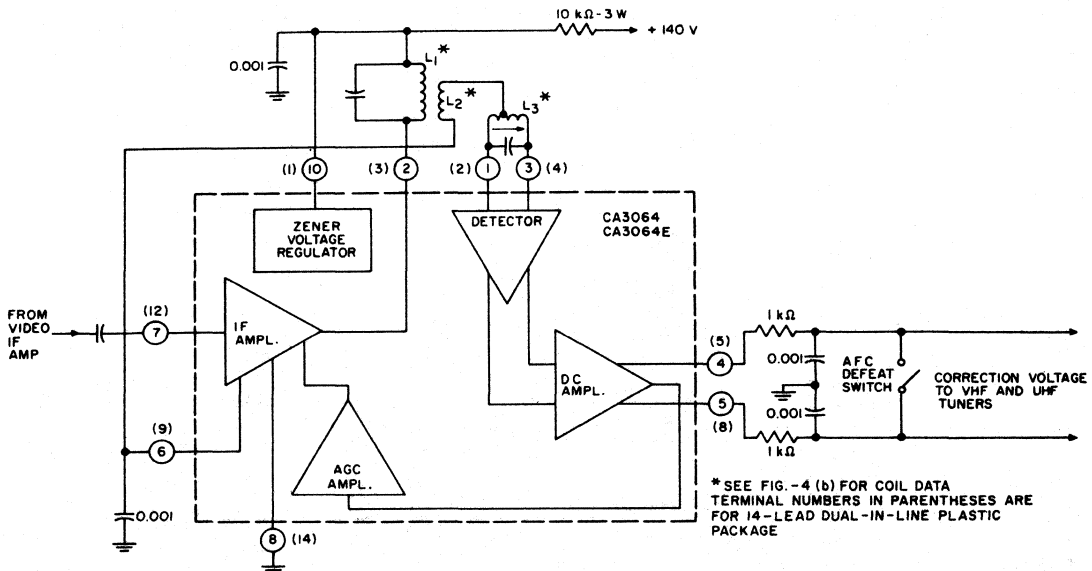


Fig. 1 - Block diagram of typical operating circuit utilizing the CA3064 and CA3064E.

92CM-15810R1

TV/CATV Circuits

CA3064, CA3064E

MAXIMUM RATINGS, Absolute-Maximum Values:

DEVICE DISSIPATION:

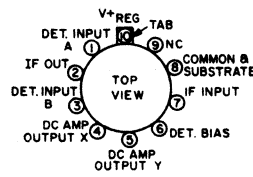
Up to $T_A = 25^\circ\text{C}$ 700 mW
 Above $T_A = 25^\circ\text{C}$ derate linearly 5.6 mW/ $^\circ\text{C}$

AMBIENT TEMPERATURE RANGE:

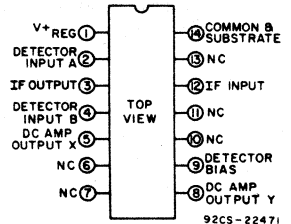
Operating -55 to $+125^\circ\text{C}$
 Storage -65 to $+150^\circ\text{C}$

LEAD TEMPERATURE (During Soldering):

At distance $1/16'' \pm 1/32''$
 (1.59 mm \pm 0.79 mm)
 from case for 10 s max.. 265 $^\circ\text{C}$



(a) CA3064



(b) CA3064E

Fig.2 — Terminal assignment diagrams.

MAXIMUM VOLTAGE RATINGS at $T_A = 25^\circ\text{C}$

The following chart gives the range of voltages which can be applied to the terminals listed vertically with respect to the terminals listed horizontally. For example, the voltage range between vertical terminal 2 (3) and horizontal terminal 6 (9) is $+20$ to 0 volts. Terminal nos. in parentheses are for the 14-lead dual-in-line plastic package.

TERMINAL No.	9(6,7,10,11,13)	10 (1)	1 (2)	2 (3)	3 (4)	4 (5)	5 (8)	6 (9)	7 (12)	8 (14)
9(6,7,10,11,13)	← NO INTERNAL CONNECTION →									
10 (1)			+12 0	+10 -10	+12 0	+12 0	+12 0	+10 0	+20 0	▲
1 (2)				*	+10 -10	*	*	+5 -5	*	+5 -6
2 (3)					*	*	*	+20 0	*	+20 0
3 (4)						*	*	+5 -6	*	+5 -6
4 (5)							*	*	*	+12 0
5 (8)								*	*	+12 0
6 (9)									+5 -2	+2 0
7 (12)										+2 -10
8 (14)										REF.SUBSTRATE & CASE

MAXIMUM CURRENT RATINGS

TERMINAL No.	I_{IN} mA	I_{OUT} mA
9(6,7,10,11,13)	-	-
10 (1)	50	50
1 (2)	1	0.1
2 (3)	20	20
3 (4)	1	0.1
4 (5)	5	5
5 (8)	5	5
6 (9)	5	5
7 (12)	1	1
8 (14)	50	50

- ▲ Terminal number 10 (1) may be connected to any positive voltage source greater than the internal zener regulating voltage through a suitable dropping resistor — provided the dissipation rating is not exceeded.
- This terminal should be connected to the most negative potential of the complete circuit.

- * Voltages are not normally applied between these terminals. Voltages appearing between these terminals will be safe if the specified limits between all other terminals are not exceeded.
- It is recommended that unused terminals 6,7,10,11, and 13 on the 14-lead dual-in-line-plastic package and terminal 9 on the TO-5 package be grounded to act as shields.

Linear Integrated Circuits

CA3064, CA3064E

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, Unless Otherwise Specified

CHARACTERISTICS	SYMBOLS	TEST CIRCUITS	TEST CONDITIONS	LIMITS CA3064, CA3064E			UNITS	CHARACTERISTIC CURVES	
				MIN.	TYP.	MAX.			
		FIG.						FIG.	
STATIC CHARACTERISTICS									
Device Dissipation	P_D	4	$V^+ = 30\text{V}$ $R_S = 1.5\text{k}\Omega$	T_A	-	135	150	mW	-
				-25°C					
				$+25^\circ\text{C}$	130	140	150		
			$+85^\circ\text{C}$	-	145	150			
Current Drain at 10.5 Volts	I_T	4	$V_{10(1)} = 10.5\text{V}$	4	6.5	9.5	mA	-	
Zener Regulated Voltage - DC Supply Voltage at terminal 10(1)*	$V_{10(1)}$	4	$V^+ = 30\text{V}$ $R_S = 1.5\text{k}\Omega$	10.9	11.8	12.8	V	-	
Quiescent Operating Current into Terminal 2(3)	$I_2(3)$	4		1	2	4	mA	-	
Quiescent Operating Voltage at Terminal 4(5)	$V_4(5)$	-		5	6.9	8	V	-	
Quiescent Operating Voltage at Terminal 5(8)	$V_5(8)$	-		5	6.9	8	V	-	
Output Offset Voltage between Terminals 4 and 5(5 and 8)	$V_{4-5(5-8)}$	-		-1	0	1	V	-	
DYNAMIC CHARACTERISTICS (AS RF AMPLIFIER IN TO-5 STYLE PACKAGE)									
Input Voltage Sensitivity	V_1 sensitivity	5	$V^+ = +30\text{V}$ $V_1 = 18\text{mV}$	Correction Voltage Output as shown in table below.					
Input Admittance	Y_{11}	-	$f = 45.75\text{MHz}$ $V^+ = 30\text{V}$ $R_S = 1.5\text{k}\Omega$	-	$0.41 + j1.0$	-	mmho	-	
Reverse Transfer Admittance	Y_{12}	-		-	$0 + j3.4$	-	μmho	-	
Forward Transfer Admittance	Y_{21}	-		-	$24.5 - j29$	-	mmho	-	
Output Admittance	Y_{22}	-		-	$0.04 + j0.9$	-	mmho	-	
OUTPUT vs FREQUENCY DEVIATION - AFC									
Correction-Control Voltage at Terminal 4(5)	V corr. 4(5)	5	$V^+ = +30\text{V}$ $V_1 = 18\text{mV RMS}$ $f_o = \text{MHz as indicated}$	% of $V_{10(1)}$		% of $V_{10(1)}$		6,7	
				45.750 - 0.030	85	-	-		V
				45.750 + 0.030	-	-	25		V
				45.750 - 0.900	80	-	-		V
				45.750 + 0.900	-	-	35		V
				45.750 - 1.500	-	-	80		V
45.750 + 1.500	35	-	-	V					
Correction-Control Voltage at Terminal 5(8)	V corr. 5(8)	5	$V^+ = +30\text{V}$ $V_1 = 18\text{mV RMS}$ $f_o = \text{MHz as indicated}$	% of $V_{10(1)}$		% of $V_{10(1)}$		6,7	
				45.750 - 0.030	-	-	25		V
				45.750 + 0.030	85	-	-		V
				45.750 - 0.900	-	-	35		V
				45.750 + 0.900	80	-	-		V
				45.750 - 1.500	35	-	-		V
45.750 + 1.500	-	-	80	V					

* Terminal numbers in parentheses are for 14-lead dual-in-line plastic package.

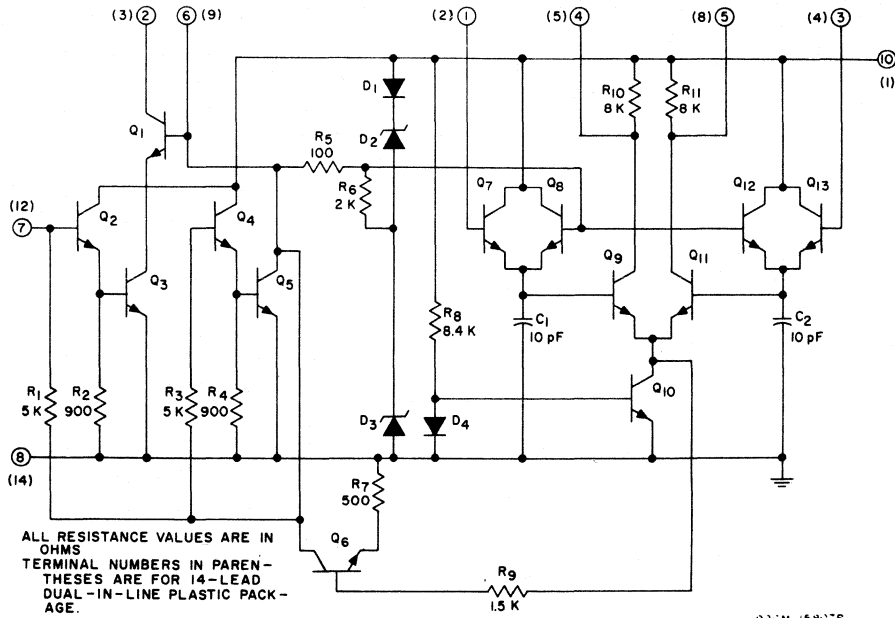


Fig.3 - Schematic diagram for CA3064 and CA3064E.

Circuit Description

The CA3064 and CA3064E integrated circuits can be considered as five functional blocks; an if amplifier-limiter, a balanced detector, a differential dc amplifier, an internally used AGC amplifier, and a zener voltage regulator. The 45-MHz amplifier limiter combination consists of emitter-follower input stage Q2 followed by a cascode-type amplifier Q1, Q3. The emitter-follower input stage Q2 is internally biased, therefore, capacitor coupling must be provided to the input at pin 7 (12). The external load is connected to pin 2 (3) and should present a load impedance of about 1800 ohms at 45.75 MHz. The detector inputs at pins 1 (2) and 3 (4)

from the external transformer are biased through the tertiary winding connected to pin 6 (9), which must be bypassed. The balanced detector is a high-efficiency type consisting of Q7/C1 and Q13/C2, which are internally biased by matching transistors Q8 and Q12. The dc amplifier consists of the differential amplifier Q9, Q10, Q11, and D4.

The amplifier detector system provides the sharply defined pull-in characteristics shown in figures 5 and 6. The AGC amplifier Q6 senses the detected signals at the collector of A10 and adjusts the gain to compensate for signal changes such as airplane flutter conditions. Diodes D1, D2, and D3 provide the internal voltage regulation.

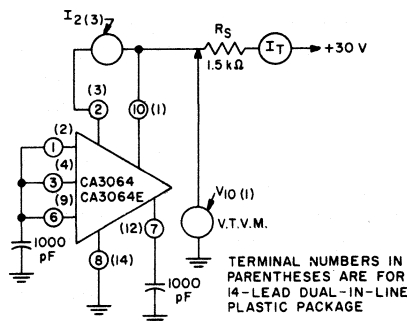
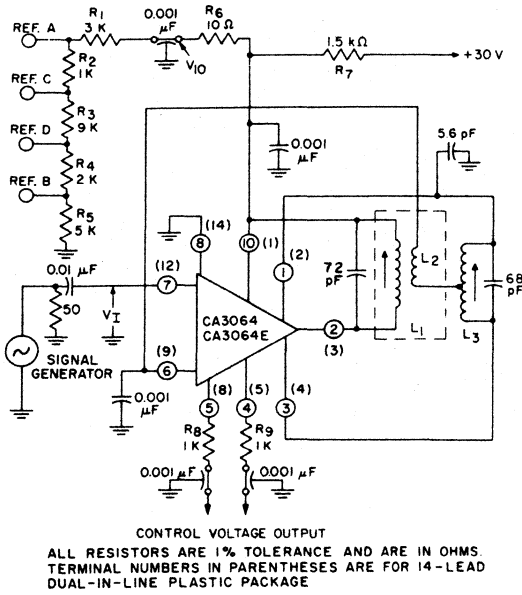


Fig.4 - Test setup: Measurement of total device dissipation, zener regulating voltage, quiescent operating current at terminal 2 (3).

CA3064, CA3064E



CONTROL VOLTAGE OUTPUT
ALL RESISTORS ARE 1% TOLERANCE AND ARE IN OHMS.
TERMINAL NUMBERS IN PARENTHESES ARE FOR 14-LEAD
DUAL-IN-LINE PLASTIC PACKAGE

92CS-15813R1

- L₁ IS ALIGNED FOR SYMMETRICAL BANDWIDTH ON EITHER SIDE OF 45.750 MHz
 - L₂ TERTIARY WINDING WOUND ON L₁ COIL FORM
 - L₃ IS ALIGNED FOR ZERO DIFFERENTIAL OUTPUT BETWEEN TERMINALS 4 AND 5 AT f₀ = 45.750 MHz
- * FOR COIL CONSTRUCTION DATA, SEE FIG. 4(b).

REFERENCE VOLTAGE PERCENTAGES	
Ref. A	85% of V ₁₀₍₁₎
Ref. B	25% of V ₁₀₍₁₎
Ref. C	80% of V ₁₀₍₁₎
Ref. D	35% of V ₁₀₍₁₎

Coil	RCA Distributor Part No.
(L ₁ , L ₂)	122 213
L ₃	122 203

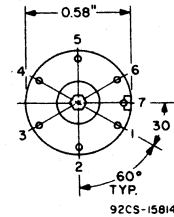


Fig.5 (b) Coil form base terminal diagram.

Fig.5 (a) – Correction voltage test circuit for CA3064 and CA3064E.

The CA3064 and CA3064E are specifically intended for use in the AFT system of color television receivers. These devices are tested so that the control voltages generated by the circuit meet the critical requirements of the system. Figure 5 (a) is the schematic diagram of the test circuit.

Figures 5, 6, and 7 show the control voltages generated at terminals 4(5) and 5(8) of the Integrated Circuit as a function of the frequency deviation from the nominal center frequency. Figure 6 shows the region within 30 kHz of the center frequency while Figure 7 covers the entire bandwidth of the system. The horizontal reference lines on the figures are generated by a voltage divider connected between the power

COIL DATA FOR DISCRIMINATOR WINDINGS

L₁ – Discriminator Primary: 3-1/6 turns; #20 Enamel-covered wire – close-wound, at bottom of coil form. Inductance of L₁ = 0.165 μH; Q₀ = 120 at f₀ = 45.75 MHz.

Start winding at terminal #6; finish at Terminal #1. See Notes below.

L₂ – Tertiary Windings: 2-1/6 turns; #20 Enamel-covered wire – close wound over bottom end of L₁. Start winding at Terminal #3; finish at Terminal #4. See Notes below.

L₃ – Discriminator Secondary: 3-1/2 turns; center-tapped, space wound at bottom of coil form.

Inductance of L₃ = 0.180 μH; Q₀ = 150 at f₀ = 45.75 MHz. Start winding at Terminal #2; finish at Terminal #5; connect center tap to Terminal #7. See Notes below.

- Notes:**
1. Coil Forms; Cylindrical; –0.30" Dia. max.
 2. Tuning Core: 0.250" Dia. x 0.37" Length.
Material: Carbinol J or equivalent
 3. Coil Form Base: See drawing below.
 4. End of coil nearest terminal board to be designated the winding start end.

supply voltage on terminal 10(1) and ground. The dynamic control voltages are compared with these references according to the Output vs Frequency Deviation Table. For example: when the frequency deviation is –30 kHz the control voltage at terminal 4(5) is greater than the reference A voltage; the control voltage at terminal 5(8) is less than the reference B voltage.

The shape of the correction voltage characteristics is dependent to a large degree upon transformer characteristics and the parts layout. In order to closely duplicate the curves shown, the printed circuit boards shown in Figures 8 and 10 and the parts layouts shown in Figures 9 and 11 should be followed as closely as possible.

TV/CATV Circuits

CA3064, CA3064E

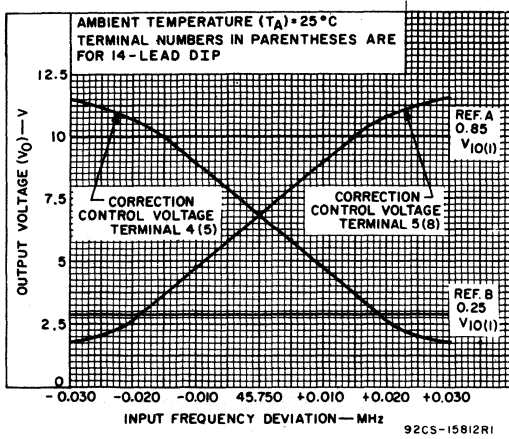


Fig. 6 — Typical narrow-band dynamic control voltage characteristics.

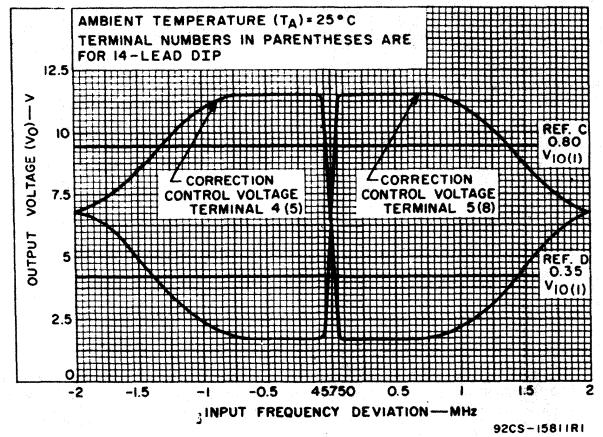


Fig. 7 — Typical wide-band dynamic control voltage characteristics.

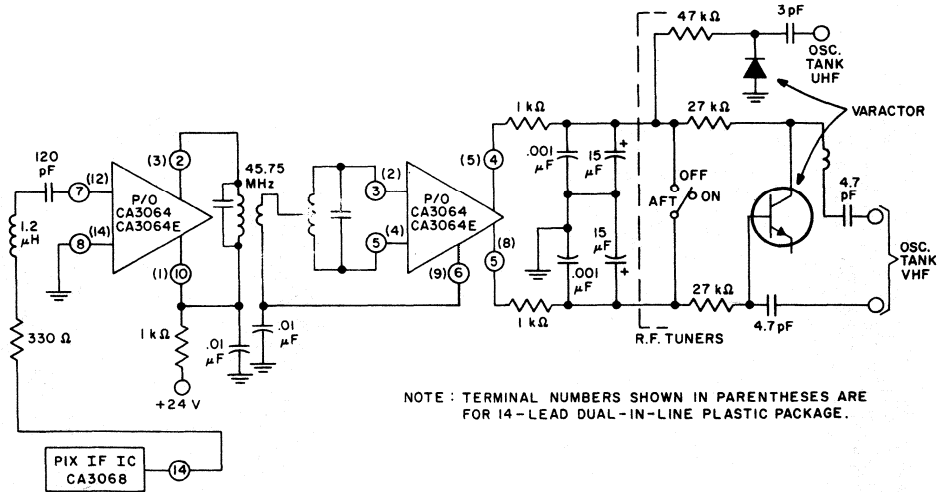
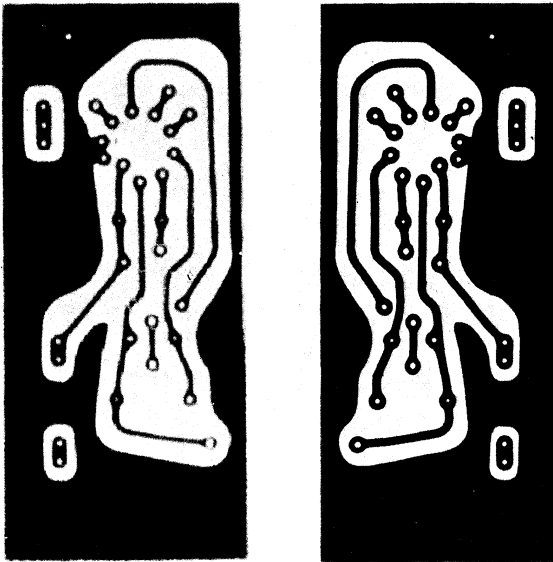


Fig. 8 — Typical application of CA3064 and CA3064E AFT IC.

Linear Integrated Circuits

CA3064, CA3064E



(a) Top view

(b) Bottom view

Fig.9 — Printed circuit board for test circuit, full size (for TO-5 style package).

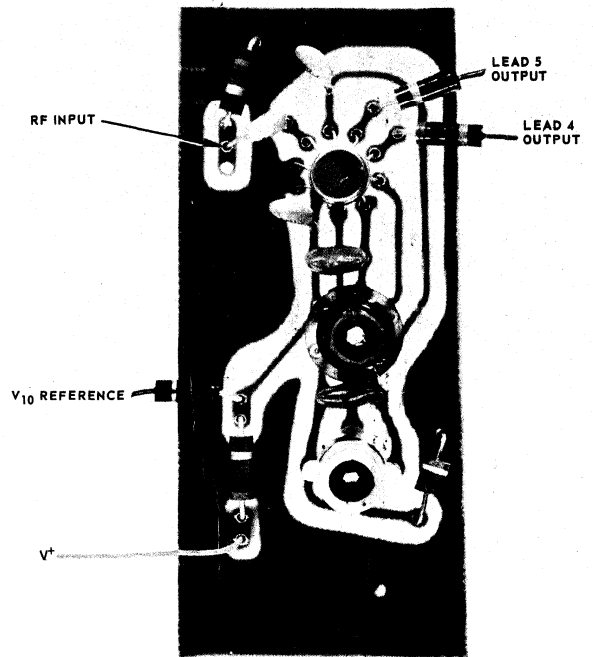
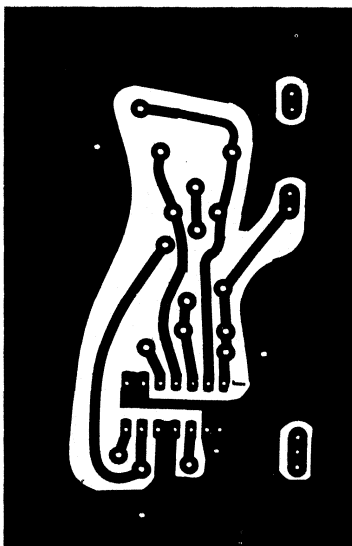
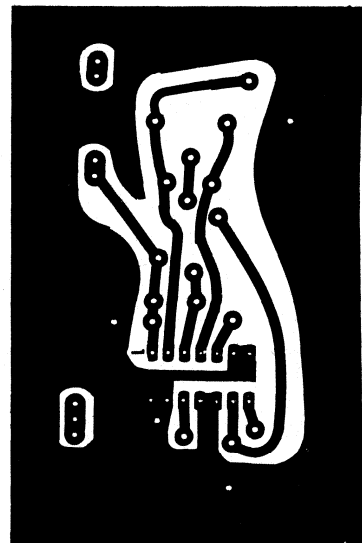


Fig.10 — Top view of wired test board (for TO-5 style package).



(a) Top view



(b) Bottom view

Fig.11 — Printed circuit board for test circuit, full size (for 14-lead dual-in-line plastic package).

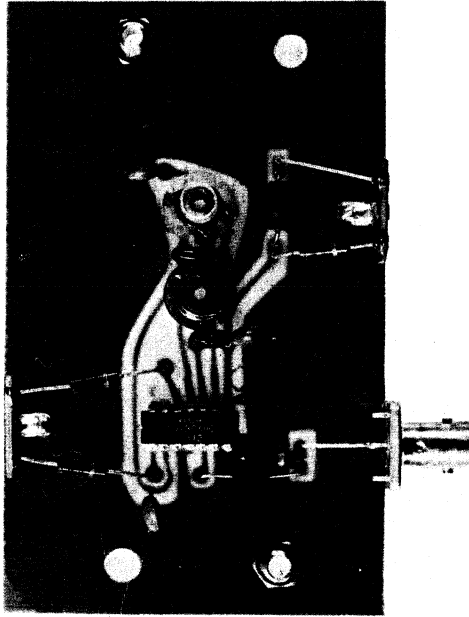
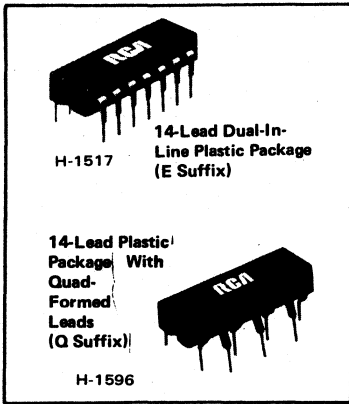


Fig.12 – Top view of wired test board (for 14-lead dual-in-line plastic package)

CA3139E, CA3139Q



TV Automatic Fine Tuning Circuit

With Intercarrier Mixer/Amplifier
For Color and Monochrome Receivers

FEATURES:

- Cascode-type high-gain amplifier (15-mV input for rated output)
 - AFT differential peak detector
 - Differential amplifier
 - Bipolar outputs
 - Five-stage intercarrier mixer/amplifier
 - Internal voltage regulator
 - For use in either color or monochrome receivers
- Platinum-silicide ohmic contacts

The RCA-CA3139 is a monolithic TV Automatic Fine Tuning (AFT) circuit that provides an AFT voltage and an amplified 4.5-MHz intercarrier sound signal. When connected to an output of an IF amplifier the CA3139 provides the signal processing (amplification and detection) necessary to generate the AFT correction signals required by the TV tuner. It also mixes the video and sound IF carriers and amplifies the resultant 4.5-MHz intercarrier sound signal. This sound output may then be connected to an FM detector such as the RCA-CA3134 "TV Sound IF and Audio Output Subsystem," or the RCA-CA3065 "FM Detector and Audio Driver."

The AFT portion of the CA3139 is similar to the RCA-CA3064 AFT circuit with the following exceptions: (a) the AFT filter capacitors are external and user selectable, allowing the detector to operate as a peak detector and resulting in a higher effective gain for the TV signal; (b) the detector bias resistor is external and user selectable, allowing the gain of the AFT and intercarrier signals to be adjusted; (c) the dynamic resistance of the shunt regulator has been decreased.

The CA3139 is supplied in a 14-lead dual-in-line plastic package (CA3139E) or a 14-lead plastic package with quad-formed leads (CA3139Q).

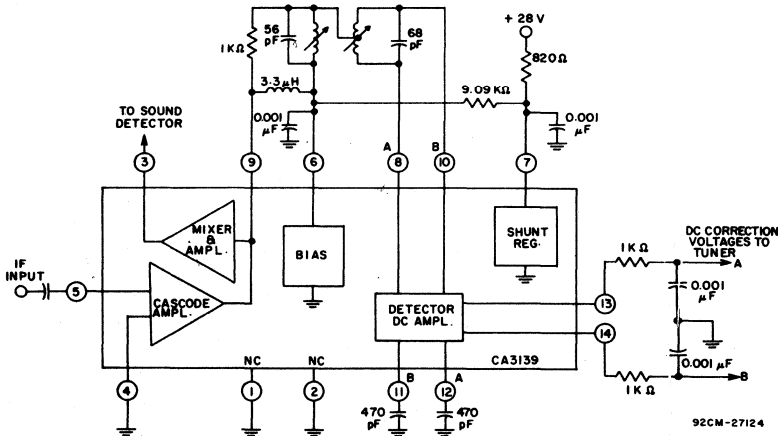


Fig. 1 - Block diagram and typical application of CA3139.

MAXIMUM VOLTAGE RATINGS at $T_A = 25^\circ\text{C}$

The following chart gives the range of voltages which can be applied to the terminals listed vertically with respect to the terminals listed horizontally. For example, the voltage range between vertical terminal 3 and horizontal terminal 12 is +8 to -1.5 volts.

Terminal No.	MAXIMUM CURRENT RATINGS													I _{IN} / I _{OUT} mA
	1,2 [♠]	3	4 [■]	5	6	7 [▲]	8	9	10	11	12	13	14	
1,2 [♠]	← NO INTERNAL CONNECTION →													
3			+10 -0	+9 -1.5	+8 -1.5	+0 -10	+8 -1.5	+8 -1.5	+8 -1.5	+8 -1.5	+8 -1.5	+8 -1.5	+8 -1.5	10
4 [■]				+0 -2	+0 -3	+0 -11	+0 -3	+0 -3	+0 -3	+0 -3	+0 -3	+0 -11	+0 -11	50
5					+0 -5	+0 -14	+2 -5	+1 -5	+2 -5	+2 -5	+2 -5	+1 -8	+1 -8	1
6						+0 -14	+2 -2	+0 -2	+2 -2	+1 -3	+1 -3	+0 -10	+0 -10	2
7 [▲]							+15 -0	+13 -0	+15 -0	+13 -0	+13 -0	+10 -0	+10 -0	50
8								+1 -5	+5 -5	+5 -5	+1 -5	+0 -14	+0 -14	2
9									+10 -2	+8 -2	+8 -2	+0 -10	+0 -10	10
10										+1 -5	+5 -5	+1 -10	+1 -10	2
11												*	*	2
12													*	2
13													+14 -14	2
14														2

- ▲ Terminal number 7 may be connected to any positive voltage source greater than the internal zener regulating voltage through a suitable dropping resistor — provided the dissipation rating is not exceeded.
- This terminal should be connected to the most negative potential of the complete circuit.

- * Voltages are not normally applied between these terminals. Voltages appearing between these terminals will be safe if the specified limits between all other terminals are not exceeded.
- ♠ It is recommended that unused terminals 1 and 2 be grounded to act as shields.

MAXIMUM RATINGS,

Absolute-Maximum Values:

DEVICE DISSIPATION:

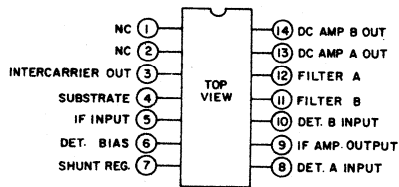
Up to $T_A = 55^\circ\text{C}$ 630 mW
Above $T_A = 55^\circ\text{C}$. derate linearly 6.67 mW/ $^\circ\text{C}$

AMBIENT TEMPERATURE:

Operating -40 to $+85^\circ\text{C}$
Storage -65 to $+150^\circ\text{C}$

LEAD TEMPERATURE (During Soldering):

At distance $1/16'' \pm 1/32''$
(1.59 mm \pm 0.79 mm)
from case for 10 s max. 265°C



92CS-27125

Fig. 2 — Terminal assignment.

Linear Integrated Circuits

CA3139E, CA3139Q

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V^+ = 28\text{ V}$ (Unless Otherwise Specified)

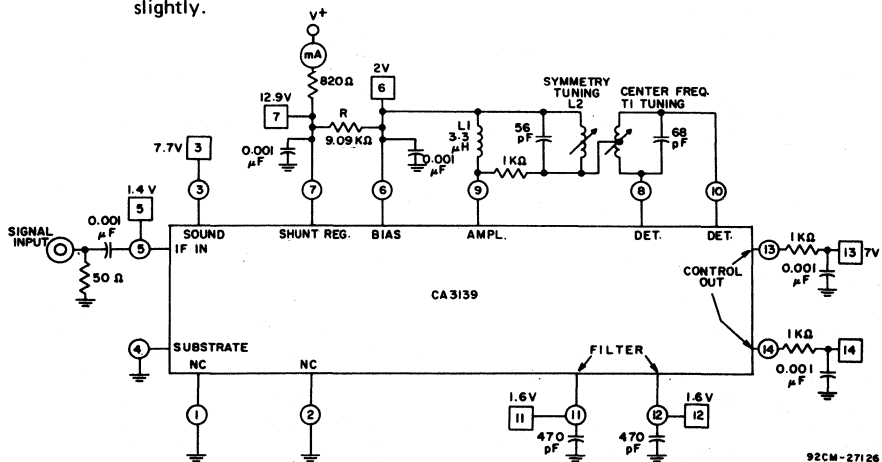
See Test Circuit, Fig. 3

CHARACTERISTIC	TEST CONDITIONS	LIMITS		UNITS
		Min.	Max.	
NO SIGNAL INPUT				
Supply Current, I^+		15	20	mA
Low Voltage at Term. 7 ¹	$V^+ = 20.8\text{ V}$	11	14.5	V
Shunt Reg. Voltage		12	14.5	V
Quiescent Voltage at Term. 3		4.5	10	V
Quiescent Voltage ² at Terms. 13 and 14	Term. 13 connected to Term. 14	6	8.5	V
Quiescent Difference Voltage, Terms. 13 to 14		-0.8	+0.8	V
Quiescent Voltage at Term. 6		1.4	2.6	V
SIGNAL INPUT = $15\text{ mV}_{\text{RMS}}$ (Unless Otherwise Specified), Note 3				
Correction Voltage at Term. 13	$f = 44.65\text{ MHz}$	2.2	4.7	V
	$f = 45.69\text{ MHz}$	1.2	4.4	
	$f = 45.81\text{ MHz}$	9.6	13.8	
	$f = 46.85\text{ MHz}$	9.1	12.1	
Correction Voltage at Term. 14	$f = 44.65\text{ MHz}$	9.1	12.1	V
	$f = 45.69\text{ MHz}$	9.6	13.8	
	$f = 45.81\text{ MHz}$	1.2	4.4	
	$f = 46.85\text{ MHz}$	2.2	4.7	
4.5 MHz Output	Two-Tone Input $f_1 = 45.75\text{ MHz}$ at 15 mV $f_2 = 41.25\text{ MHz}$ at 5 mV	50	200	mV_{RMS}

NOTES: 1. $I_7 = 12\text{ mA}$ maximum at $V_7 = 11\text{ V}$.

2. $V_{13} = 0.55\text{ V}_Z \pm 0.7\text{ V}$

3. Resistor from term. 6 to term. 7 = $9.09\text{ K}\Omega$. Crossover steepens and "bow tie" width increases when resistor is decreased in value. Total peak swing decreases slightly.



NOTES:

1. Use $10\text{ K}\Omega$ Isolation Resistor at DC Voltmeter Probe Tip When Making DC Measurements.
2. Typical No-Signal DC Potentials Are Shown.
3. Boxes Represent Test Points.

L1: RCA P.N. 122205

L2: RCA P.N. 14133

4½ Turns #22 Wire, O.D. = 0.25" (Typ.)

Q (Unloaded) = 100 (Min.)

f = 41.25 MHz

Inductance = 0.18 μH (Typ.)

T1: RCA P.N. 140607

3½ Turns (Center Tapped) #20 Wire,

O.D. = 0.36" (Typ.)

Q (Unloaded) = 140 (Min.)

f = 45.75 MHz

Inductance = 0.18 μH (Typ.)

Fig. 3 - Test circuit.

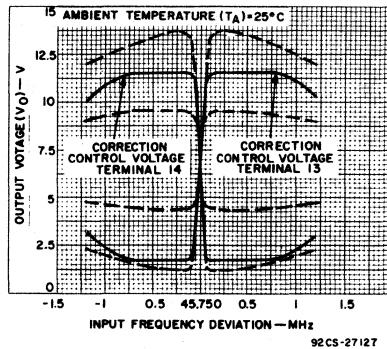


Fig. 4 – Dynamic control-voltage characteristics.

CIRCUIT DESCRIPTION

The CA3139 consists of five functional circuits as shown in the block diagram, Fig. 1 (see Fig. 5 for schematic diagram).

- 1) **Cascode Amplifier** – Consists of emitter-follower Q1, common-emitter amplifier Q2, and common-base amplifier Q3.
- 2) **Bias Circuit** – Consists of Q4 and resistors R1, R4, R5, and an external resistor (user selectable) connected to the voltage regulator, terminal 7. The nominal value of the external resistor is 9.1 kΩ. Reduced values will raise the gain of the cascode amplifier chain, and higher values will reduce the gain. If the gain is increased, the AFT “Bow Tie” width will increase and the crossover slope will increase (become steeper). The input transistor Q1 is internally biased, so AC coupling is normally used to the input terminal 5.
- 3) **Inter-carrier Mixer/Amplifier** – The output of the cascode amplifier at terminal 9 is also internally connected to the inter-carrier mixer/amplifier chain consisting of transistors Q13 through Q17 and associated components. The video IF carrier at 45.75-MHz and the FM sound IF carrier at 41.25-MHz are down-converted to a 4.5-MHz FM signal by Q14. A low-pass

filter removes the carriers and upper conversion signal components. The 4.5-MHz FM signal is further amplified and filtered by Q16 and C3. The FM sound output signal is at terminal 3. The gain with respect to a 5-mV sound carrier (tested with a 15-mV video carrier) input signal at terminal 5 is 10 to 40 when the resistor is connected between terminals 6 and 7 is 9.09 kΩ.

- 4) **AFT Detector and DC Amplifier** – Consists of Q6 through Q12 and related components. The detector inputs at terminals 8 and 10 are connected to the external discriminator transformer and biased through the transformer at terminal-6 potential. The total current through transistors Q7 and Q8 is held constant by the current-mirror transistors Q10, Q11, and Q12. External filter capacitors connected to terminals 11 and 12 assure that peak detection is accomplished. The AFT output voltages are shown in the Electrical Characteristics chart, and a graphical representation is shown in Fig. 4.
- 5) **Voltage Regulator** – An active shunt regulator, consisting of D1, D2, Z1, Z2, and Q5, is included to reduce the dynamic resistance.

Linear Integrated Circuits

CA3139E, CA3139Q

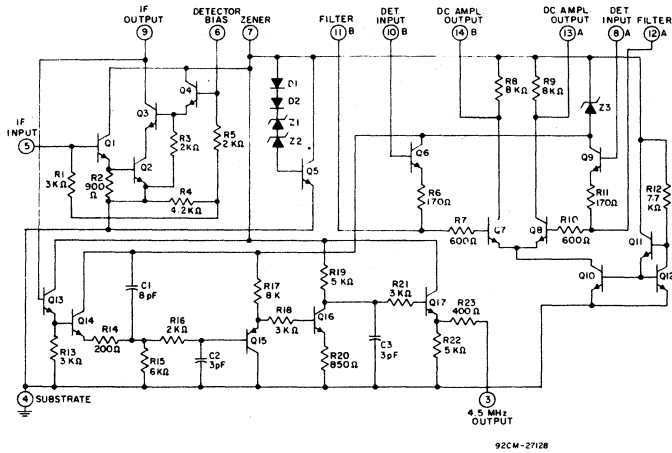


Fig. 5 - Schematic diagram of CA3139.

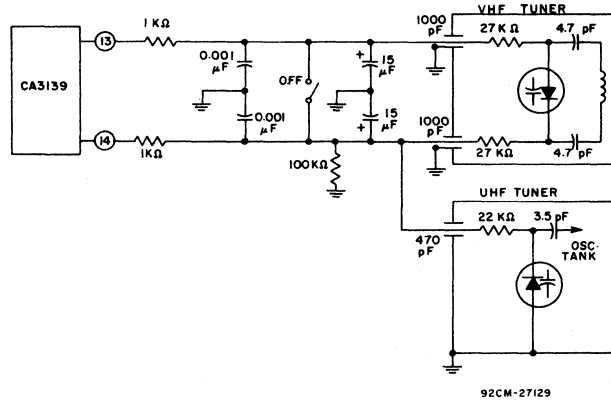
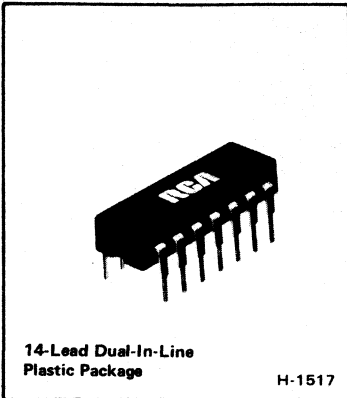


Fig. 6 - Typical tuner connection.

Television Chroma Processor



14-Lead Dual-In-Line
Plastic Package

H-1517

Features

- Minimum number of external components required
- Injection-lock oscillator with internal feedback
- DC chroma gain control and hue control circuits
- Low-impedance internal voltage regulation

RCA-CA1398E is a monolithic silicon integrated-circuit chroma processor containing chroma-amplifier and gain-control, color-killer, color subcarrier oscillator, hue control, and ACC circuitry. It has been designed for interchangeability with other "1398"-type chroma-processor devices. It functions compatibly with the RCA-CA3125E Chroma Demodulator as well as other commercially available chroma demodulators in color-TV receivers. Fig. 2 shows a functional block diagram of a 2-package TV chroma system incorporating the CA1398E and CA3125E. The CA1398E is supplied in a 14-lead dual-in-line plastic package.

Maximum Ratings, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

Peak Horizontal-Pulse Input Current	250 μA
Supply Current (Terminal 14)	35 mA
Ambient Temperature Range:	
Operating	-40 to +85 $^\circ\text{C}$
Storage	-65 to +150 $^\circ\text{C}$
Lead Temperature (During Soldering):	
At distance 1/16" \pm 1/32" (1.59 \pm 0.79 mm)	265 $^\circ\text{C}$
from case for 10 s max.	

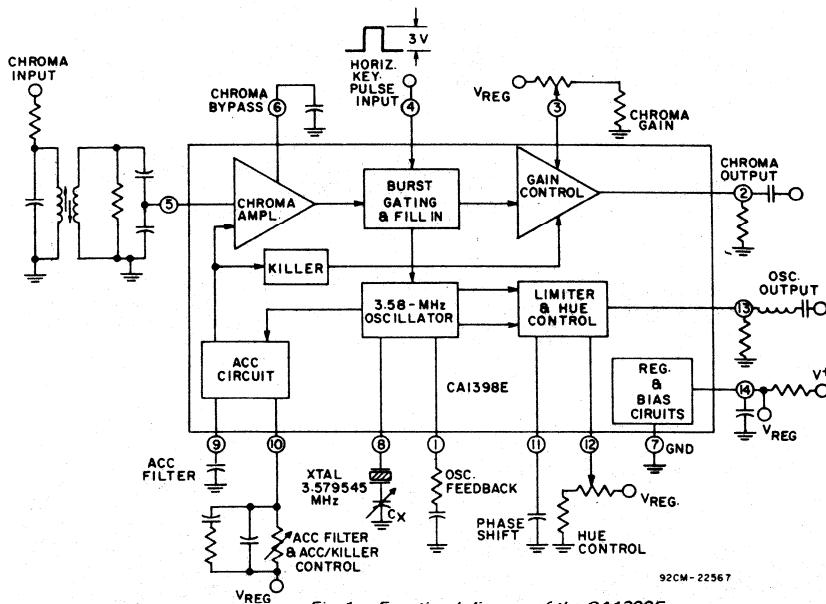


Fig. 1 - Functional diagram of the CA1398E.

Linear Integrated Circuits
CA1398E

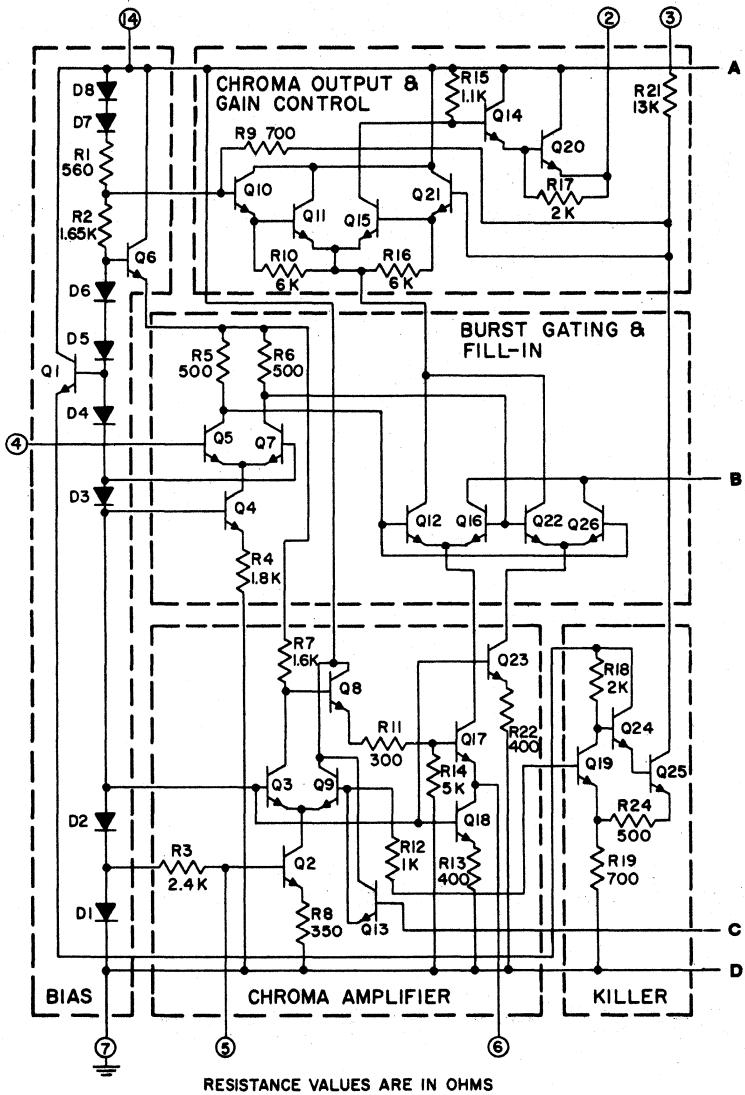
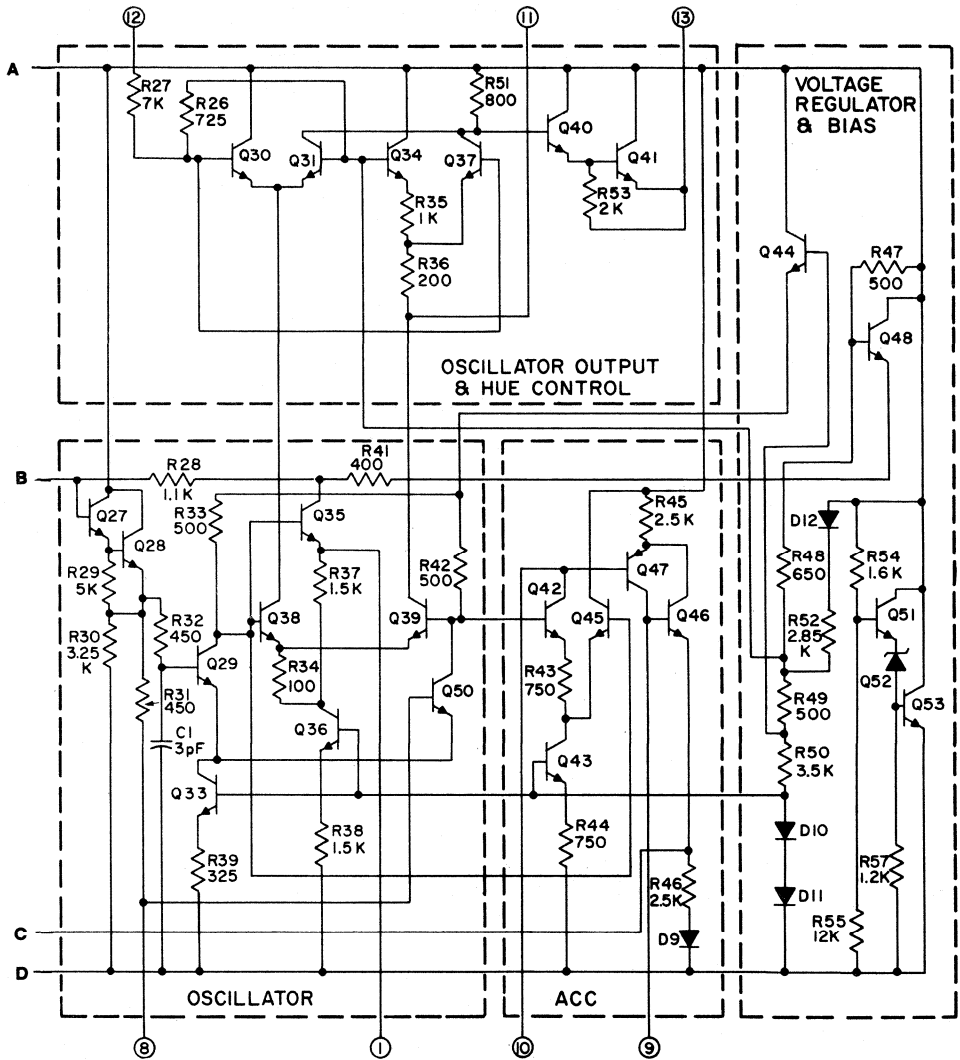


Fig. 2— Schematic diagram of the CA1398E (cont'd on next page).



92CL-22523

Fig. 2- Schematic diagram of the CA1398E (cont'd from previous page).

Linear Integrated Circuits

CA1398E

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$ and Referenced to Test Circuit (Fig. 4)

CHARACTERISTIC	TERMINAL MEASURED AND SYMBOL	TEST CONDITIONS					LIMITS			UNITS		
		SWITCH POSITION (S1)	CONTROL SETTING			V_{BURST} mV p-p	V_{CHROMA} mV p-p	MIN.	TYP.		MAX.	
			CHROMA	HUE	KILLER							
<i>Static Characteristics</i>												
Regulated Supply Voltage	V ₁₄	2	max.	max.	max.	0	0	8.9	9.5	11.5	V	
Chroma Output Bias	V ₁₄ to V ₂	2	max.	max.	max.	6	0	1.2	2.4	3.6	V	
Regulator Impedance	See Note 1	2	max.	max.	max.	0	0	—	12	25	Ω	
<i>Dynamic Characteristics (Refer to Test Set-Up Procedure for Oscillator)</i>												
Max. Chroma Gain	V ₂	1	max.	max.	See Note 2	6	5	310	425	—	mV p-p	
Min. Chroma Gain	V ₂	1	min.	max.		6	5	—	—	7	—	mV p-p
ACC Action	V ₂ (dB up from gain test)	1	max.	max.		50	50	2	7	11	—	dB
Killer Function:												
Kill	V ₂	2	max.	max.		0	5	—	—	7	—	mV p-p
Unkill	V ₂	1	max.	max.		15	5	100	—	—	—	mV p-p
Oscillator Lock-Up:												
Voltage	V ₁₃	1	max.	max.		6	0	250	340	390	—	mV p-p
Phase (Referenced to burst)	ϕ_{13}	1	max.	max.		6	0	-20	0	+20	—	degrees
Hue Control Range:												
Voltage	V ₁₃	1	max.	min.	6	0	250	340	390	—	mV p-p	
Phase (Referenced to burst)	ϕ_{13}	1	max.	min.	6	0	95	110	140	—	degrees	

Note 1 — Measure V_{14} at $I_{\text{SUPPLY}} = 38 \text{ mA}$ and 18 mA . Calculate the regulator impedance:
 $Z_{\text{reg.}} = [V_{14} \text{ (at } 38 \text{ mA)} - V_{14} \text{ (at } 18 \text{ mA)}] / 0.02$

Note 2 — Increase the killer potentiometer resistance from minimum until the circuit unkills. This condition is evidenced by a shift in bias voltage at Term. 6. Maintain this potentiometer setting for all the dynamic tests.

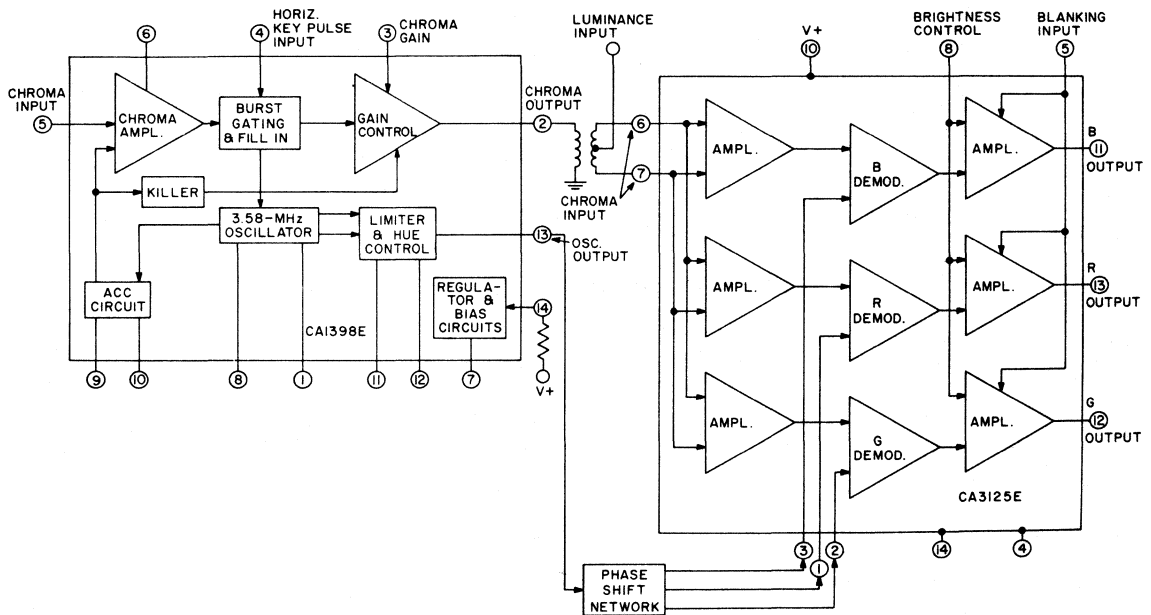


Fig. 3 - TV chroma system functional block diagram.

92CL - 22548

TEST SET-UP PROCEDURE FOR OSCILLATOR

Remove the horizontal keying and chroma inputs and adjust C_X to obtain a free-running oscillator frequency of 3.579545

MHz ± 10 Hz. Under the same Test Conditions described in the Electrical Characteristics Chart for Oscillator Lock-Up, vary L1 (approx. 20 μ H) and/or C1 (approx. 1000 pF) to obtain the initial conditions for amplitude and phase oscillator lock-up.

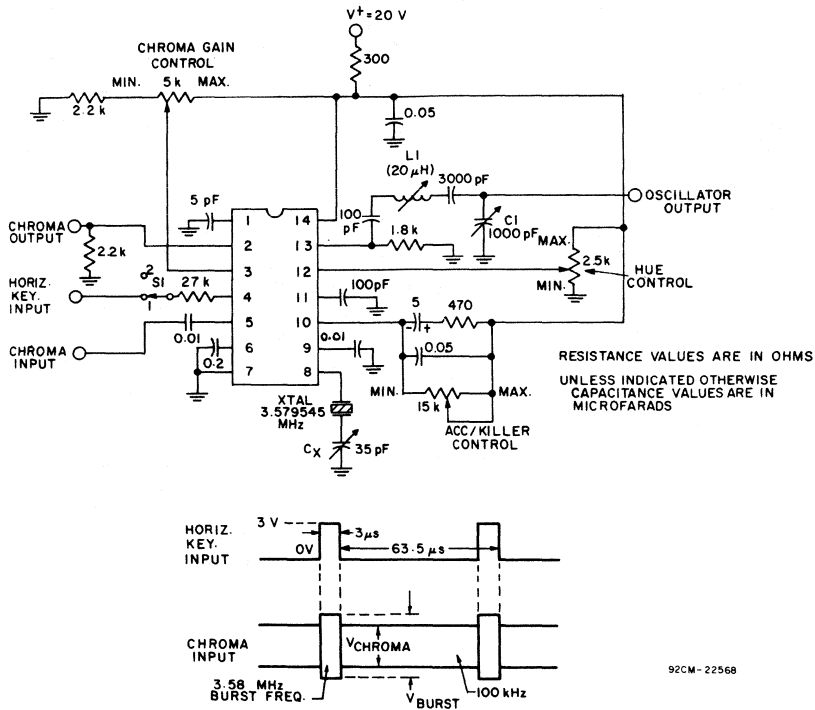
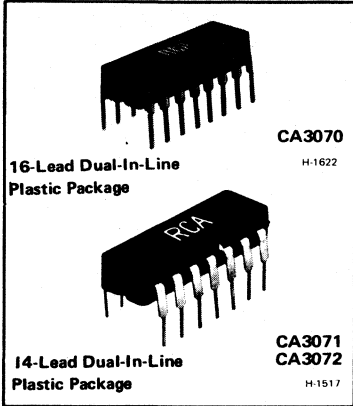


Fig. 4 - Typical static and dynamic characteristics test circuit for the CA1398E.

CA3070, CA3071, CA3072 Types

Television Chroma System



SYSTEM FEATURES

CA3070

- Voltage Controlled Oscillator
- Keyed APC & ACC Detectors
- DC Hue Control
- Shunt Regulator

CA3071

- ACC Controlled Chroma Amplifier
- DC Chroma Gain Control
- Color Killer
- Amplifier Short-Circuit Protection

CA3072

- Synchronous Detector with Color Difference Matrix
- Emitter-Follower Output Amplifiers with Short-Circuit Protection

The RCA CA3070, CA3071, and CA3072 are monolithic silicon integrated circuits that constitute a complete chroma system for color television receivers. The CA3070 is a complete subcarrier regeneration system featuring a new concept of phase control applied to the oscillator circuit. The CA3071 is a chroma amplifier system and the CA3072 performs the demodulation function.

The CA3070 utilizes the 16-lead plastic dual-in-line package; the CA3071 and CA3072 are supplied 14-lead plastic dual-in-line packages.

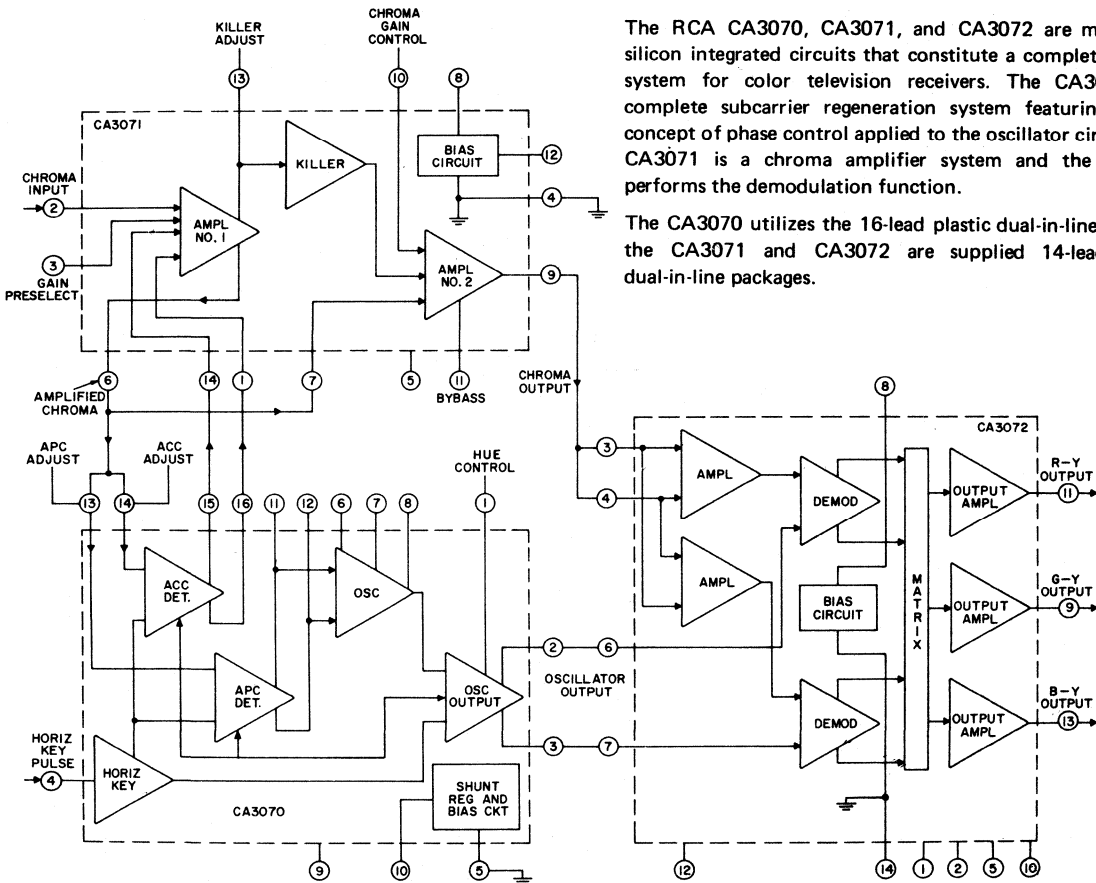


Fig. 1 - Simplified block diagram of TV chroma system.

92CL-17574R1

CA3070 Chroma Signal Processor

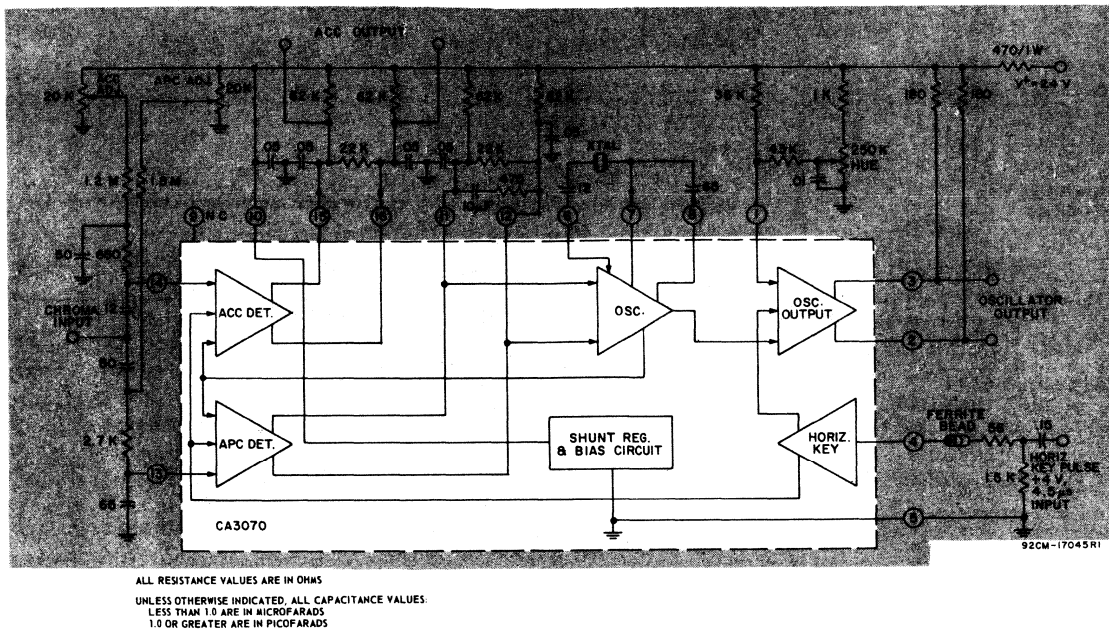


Fig. 2 – Functional diagram of RCA-CA3070.

The CA3070 is a complete subcarrier regeneration system with automatic phase control applied to the oscillator. An amplified chroma signal from the CA3071 is applied to terminals No. 13 and No. 14, which are the automatic phase control (APC) and the automatic chroma control (ACC) inputs. APC and ACC detection is keyed by the horizontal pulse which also inhibits the oscillator output amplifier during the burst interval.

The ACC system uses a synchronous detector to develop a correction voltage at the differential output terminal Nos. 15 & 16. This control signal is applied to the input terminal Nos. 1 & 14 of the CA3071. The APC system also uses a synchronous detector. The APC error voltage is internally coupled to the 3.58 MHz oscillator at balance; the phase of the signal at terminal No. 13 is in quadrature with the oscillator.

To accomplish phasing requirements, an RC phase shift network is used between the chroma input and terminal Nos. 13 and 14. The feedback loop of the oscillator is from terminal Nos. 7 and 8 back to No. 6. The same oscillator

signal is available at terminal Nos. 7 and 8, but the dc output of the APC detector controls the relative signal levels at terminal Nos. 7 or 8. Because the output at terminal No. 8 is shifted in phase compared to the output at terminal No. 7, which is applied directly to the crystal circuit, control of the relative amplitudes at terminal Nos. 7 and 8 alters the phase in the feedback loop, thereby changing the frequency of the crystal oscillator. Balance adjustments of dc offsets are provided to establish an initial no-signal offset control in the ACC output, and a no-signal, on-frequency adjustment through the APC detector-amplifier circuit which controls the oscillator frequency. The oscillator output stage is differentially controlled at terminal Nos. 2 and 3 by the hue control input to terminal No. 1. The hue phase shift is accomplished by the external R, L, and C components that couple the oscillator output to the demodulator input terminals. The CA3070 includes a shunt regulator to establish a 12-volt dc supply.

Linear Integrated Circuits

CA3070, CA3071, CA3072 Types

MAXIMUM RATINGS, Absolute Maximum-Values at $T_A = 25^\circ\text{C}$

DC Supply Voltage and Current See Charts Below

Device Dissipation:

Up to $T_A = +70^\circ\text{C}$ 530 mW

Above $T_A = +70^\circ\text{C}$. . . Derate Linearly at $6.7\text{ mW}/^\circ\text{C}$

Ambient Temperature Range:

Operating -40 to $+85$ $^\circ\text{C}$

Storage -65 to $+150$ $^\circ\text{C}$

Lead Temperature (During Soldering):

At distance $1/32$ in. (3.17 mm) from seating plane
for 10 s max. $+265$ $^\circ\text{C}$

Maximum Voltage and Current Ratings at $T_A = +25^\circ\text{C}$

Voltage[▲]

Terminal No.	Min. Volts	Max. Volts
1	0	*
2	0	+16
3	0	+16
4	-5	N2
6	-	-
7	-	-
8	-	-
10	0	N3
11	0	N1
12	0	N1
13	0	N1
14	0	N1
15	0	+16
16	0	+16

Current

Terminal No.	I_I mA	I_O mA
1	20	1
2	-	-
3	-	-
4	20	1
10	N3	1
11	-	-
12	-	-
13	20	1
14	20	1

▲ With respect to terminal No.5 and with terminal No. 10 connected through 470Ω to $+24\text{ V}$.

N1 Regulated voltage at terminal No. 10.

N2 Controlled by max. input current.

N3 Limited by dissipation.

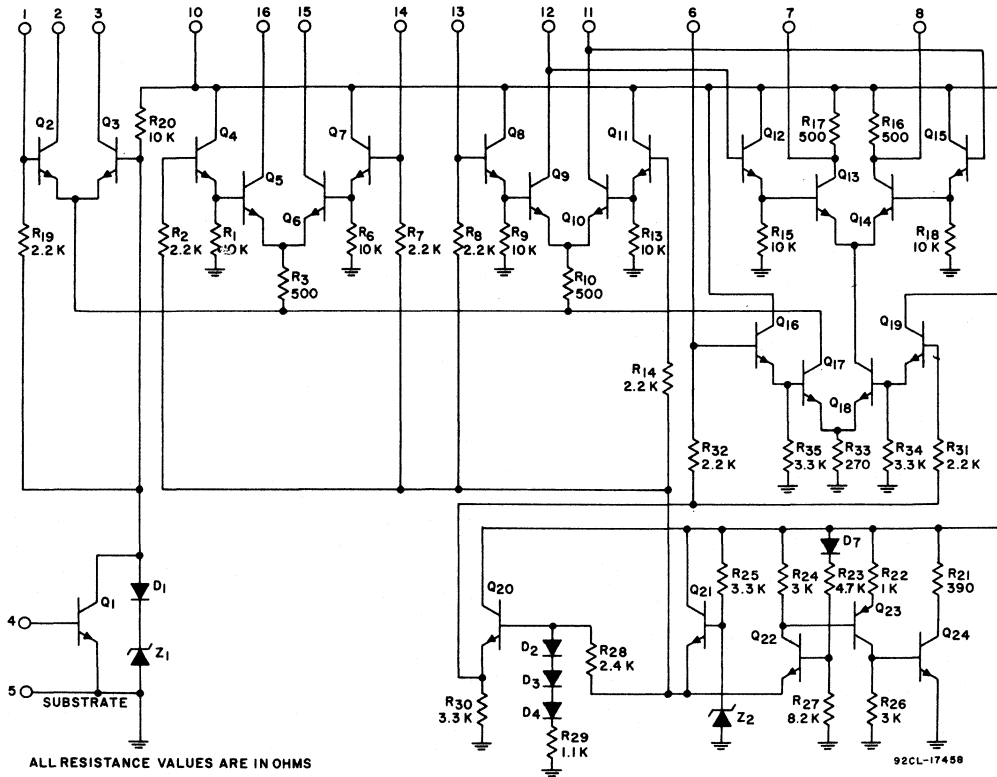


Fig. 3 — Schematic diagram CA3070.

TV/CATV Circuits

CA3070, CA3071, CA3072 Types

ELECTRICAL CHARACTERISTICS, at $T_A = 25^\circ\text{C}$ and $V^+ = +24\text{ V}$ unless otherwise specified

CHARACTERISTICS	SYMBOLS	SPECIAL TEST CONDITIONS	LIMITS			UNITS	TEST CIRCUITS
			CA3070				
			MIN.	TYP.	MAX.	FIG.	

Static Characteristics

Voltage:								
Hue Control	V_1	Switch in position 2	6.9	7.7	8.6	V	4c	
Oscillator Input	V_6		—	2.8	—			4a
APC Input	V_{13}		—	6.5	—			
Regulator	V_{10}	$V^+ = 21\text{ V}$	11	12.3	13.5			
Regulator Change	V_{10}	$V^+ = 27\text{ V}$	-0.2	—	+0.2			
Horizontal Key Input	V_4	$I_4 = -10\ \mu\text{A}$	5	—	—			
Currents:								
Oscillator Output	I_2		—	5.8	—	mA	4c	
APC Output	I_{11}, I_{12}		—	1.45	—			4b
ACC Output	I_{15}, I_{16}		—	1.45	—			

Dynamic Characteristics

Oscillator Outputs:							
Terminal No. 2	V_2	S_1 in position 1	0.75	1.0	—	V_{p-p}	5
Terminal No. 3	V_3	S_1 in position 2	0.75	1.0	—		
ACC Detected Output	$V_{16}-V_{15}$	S_1 in position 1	115	150	—	mV	5
Oscillator Pull-In Range	—		—	± 400	—	Hz	5

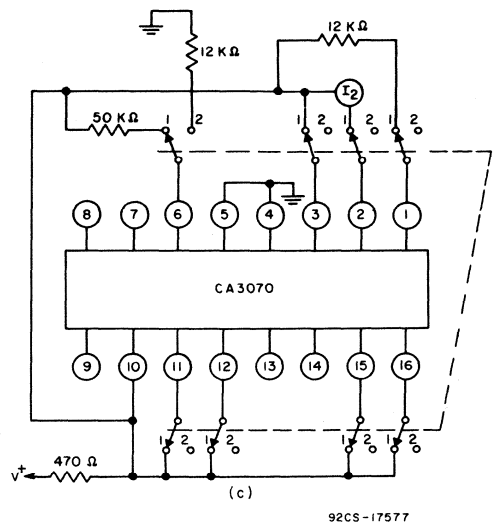
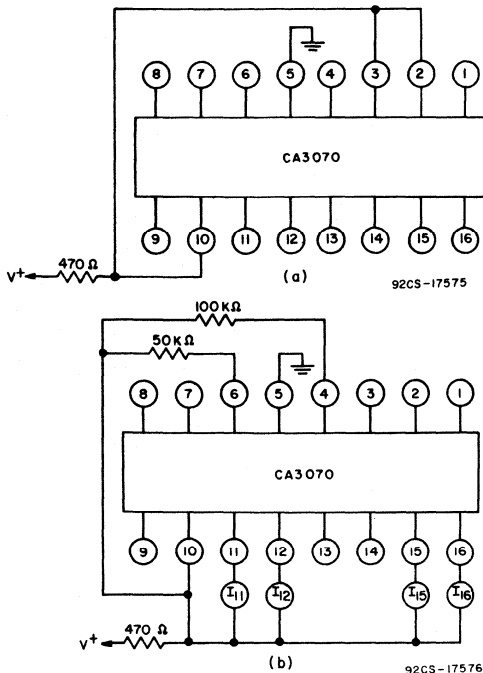
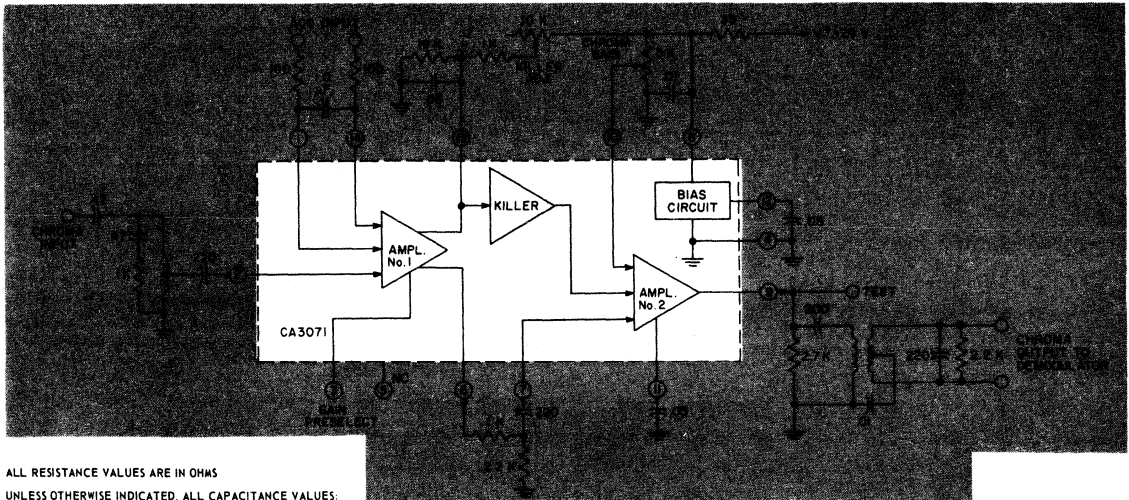


Fig. 4 — Static characteristics test circuits.

CA3071 Chroma Amplifier



ALL RESISTANCE VALUES ARE IN OHMS
UNLESS OTHERWISE INDICATED, ALL CAPACITANCE VALUES:
LESS THAN 1.0 ARE IN MICROFARADS
1.0 OR GREATER ARE IN PICOFARADS

Fig. 7 - Functional diagram of RCA-CA3071.

92CM-17044 R1

The CA3071 is a combined two-stage chroma amplifier and functional control circuit. The input signal is received from the video amplifier and applied to terminal No. 2 of the input amplifier stage. The first amplifier stage is part of the ACC system and is controlled by differential adjustment from the ACC input terminal Nos. 1 and 14. The output of the 1st amplifier is directed to terminal No. 6 from where the signal may be applied to the ACC detection system of the CA3070 or an equivalent circuit. The output at terminal No. 6 is also applied to terminal No. 7 which is the input to the 2nd amplifier stage. Another output of the 1st amplifier at terminal No. 13 is directed to the killer adjustment circuit.

The dc voltage level at terminal No. 13 rises as the ACC differential voltage decreases with a reduction in the burst amplitude. At a pre-set condition determined by the killer adjustment resistor the killer circuit is activated and causes the 2nd chroma amplifier stage to be cut off. The 2nd chroma amplifier stage is also gain controlled by the adjustment of dc voltage at terminal No. 10. The output of the 2nd chroma amplifier stage is available at terminal No. 9. The typical output termination circuit that is shown, provides differential chroma drive signal to the demodulator circuit. Both amplifier outputs utilize emitter-followers with short-circuit protection.

MAXIMUM RATINGS, Absolute Maximum-Values at $T_A = 25^\circ\text{C}$

DC Supply Voltage (Terminal 8 to Terminal 4)	30	VDC
Device Dissipation:		
Up to $T_A = +70^\circ\text{C}$	530	mW
Above $T_A = +70^\circ\text{C}$	Derate Linearly at 6.7 mW/ $^\circ\text{C}$	
Ambient Temperature Range:		
Operating	-40 to +85	$^\circ\text{C}$
Storage	-65 to +150	$^\circ\text{C}$
Lead Temperature (During Soldering):		
At distance 1/32 in (3.17 mm) from seating plane for 10 s max.	+265	$^\circ\text{C}$

Maximum Voltage and Current Ratings @ $T_A = +25^\circ\text{C}$

Terminal No.	I_I mA	I_O mA
1	5	1.0
2	5	1.0
3	10	10
6	1.0	20
7	5	1.0
9	1.0	20
12	1.0	5
14	5	1.0

Terminal No.	MIN VOLTS	MAX VOLTS
1	-5	+15
2	-5	+5
3	0	+2
6	0	+24
7	-5	+5
8	0	+30
9	0	+24
10	0	+24
11	0	+24
12	0	+20
13	0	+20
14	-5	+15

* With reference to terminal No. 4 and with +24 V on terminal No. 8 except for the rating given for terminal No. 8.

TV/CATV Circuits

CA3070, CA3071, CA3072 Types

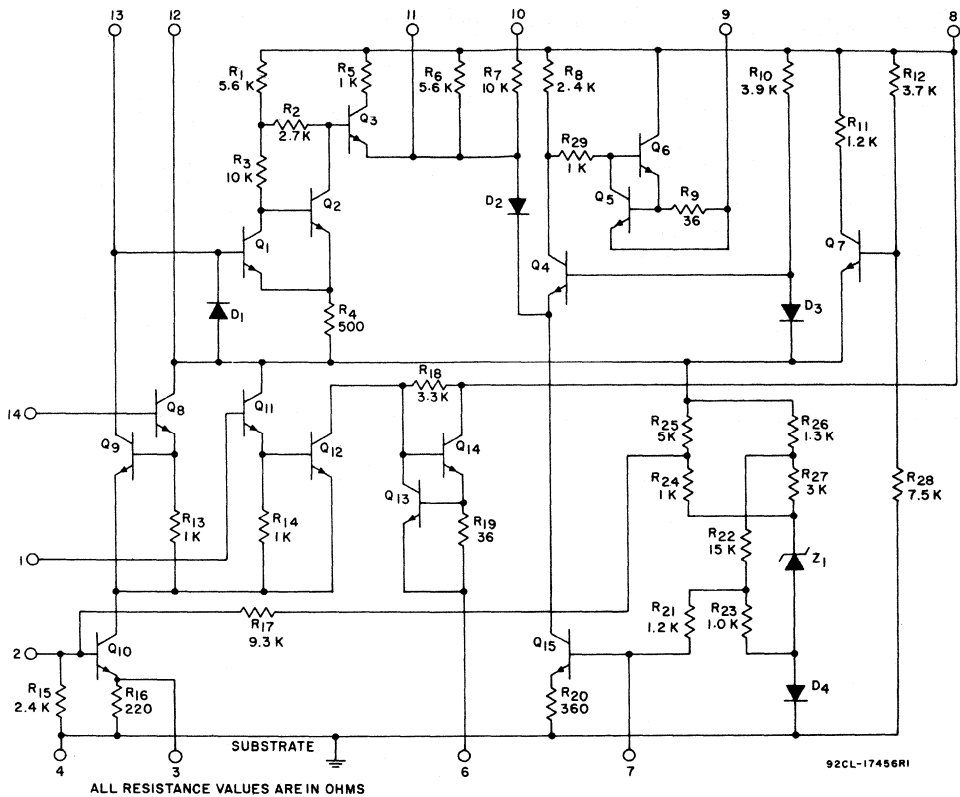


Fig. 10—Schematic diagram for CA3071.

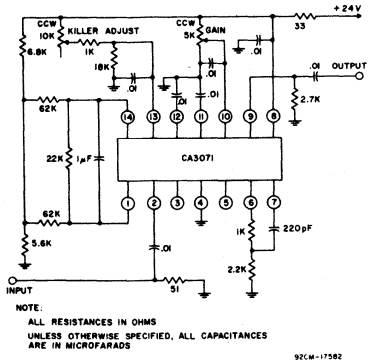


Fig. 11 — CA3071 Wideband amplifier circuit.

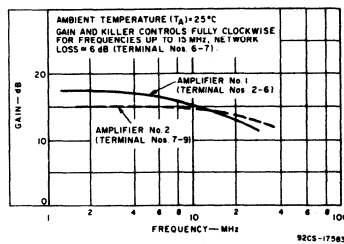


Fig. 12 — Frequency response for wideband amplifier CA3071.

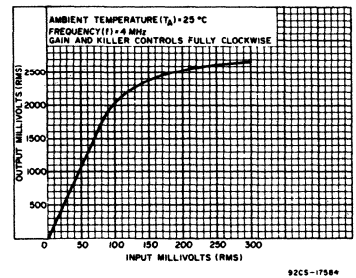


Fig. 13 — Typical CA3071 wideband amplifier linearity

Linear Integrated Circuits

CA3070, CA3071, CA3072 Types

CA3072 Chroma Demodulator

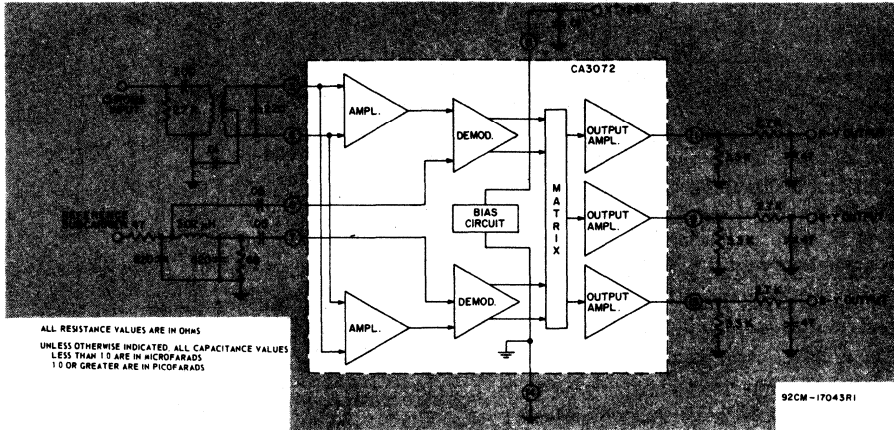


Fig. 14 — Functional diagram of RCA-CA3072.

The CA3072 has two sets of synchronous detectors with matrix circuits to achieve the R-Y, G-Y, and B-Y color difference output signals. The chroma input signal is applied to terminal Nos. 3 and 4 while the oscillator injection signal is applied to terminal Nos. 6 and 7. The color difference signals, after matrix, have a fixed relationship of amplitude

and phase nominally equal dc voltage levels. The outputs of the CA3072 are suitable for driving high level color difference or R, G, B output amplifiers. Emitter-follower output stages used to drive the high level color amplifiers have short-circuit protection.

MAXIMUM RATINGS, Absolute Maximum-Values at $T_A = 25^\circ C$

DC Supply Voltage (Terminal 8 to Terminal 14).....	27	V
Reference Input Voltage.....	5	V _{p-p}
Chroma Input Voltage.....	5	V _{p-p}
Device Dissipation:		
Up to $T_A = +70^\circ C$	530	mW
Above $T_A = +70^\circ C$	Derate Linearly at 6.7 mW/ $^\circ C$	
Ambient Temperature Range:		
Operating.....	-40 to +85	$^\circ C$
Storage.....	-65 to +150	$^\circ C$
Lead Temperature (During Soldering):		
At distance 1/32 in (3.17 mm) from seating plane		
for 10 s max.....	+265	$^\circ C$

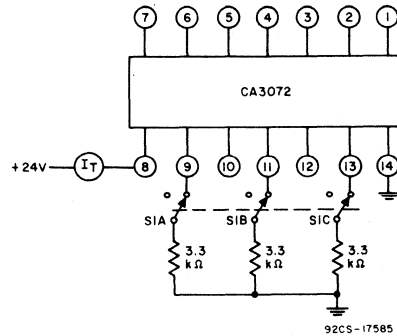


Fig. 15 — Static characteristics test circuit—CA3072.

Maximum Voltage and Current Ratings at $T_A = +25^\circ C$

Voltage*			Current		
Terminal No.	MIN VOLTS	MAX VOLTS	Terminal No.	I _I mA	I _O mA
3	0	+5	3	—	—
4	0	+5	4	—	—
6	0	+12	6	—	—
7	0	+12	7	—	—
8	0	+27	8	—	—
9	0	+20	9	1.0	20
11	0	+20	11	1.0	20
13	0	+20	13	1.0	20

*With reference to terminal No. 14 and with the voltage between terminal No. 8 and terminal No. 14 at +24 V except as given in rating for terminal No. 8.

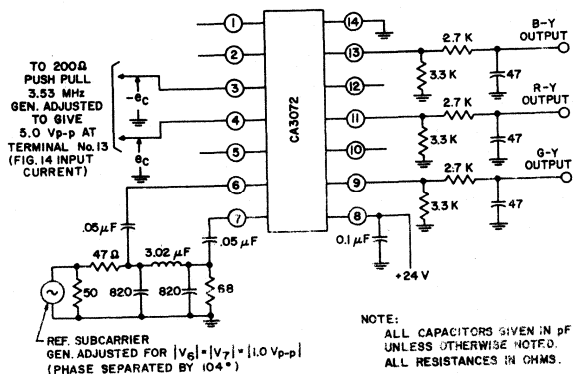


Fig. 16 — Dynamic characteristics test circuit for CA3072.

TV/CATV Circuits

CA3070, CA3071, CA3072 Types

ELECTRICAL CHARACTERISTICS, at $T_A = 25^\circ\text{C}$ and $V^+ = +24\text{ V}$ unless otherwise specified

CHARACTERISTICS	SYMBOLS	SPECIAL TEST CONDITIONS	LIMITS CA3072			UNITS	TEST CIRCUITS FIG.
			MIN.	TYP.	MAX.		

Static Characteristics

Supply Current With Output Loads	I_T	S_1 Closed	16.5	—	26.5	mA	15
With No Output Loads		S_1 Open	—	9			
G-Y, R-Y, B-Y Outputs	V_9, V_{11}, V_{13}	S_1 Closed	13.2	14.7	15.8	V	
Chroma Inputs	V_3, V_4	S_1 Open	—	3.3	—		
Reference Subcarrier	V_6, V_7	S_1 Open	—	6.2	—		

Dynamic Characteristics

Demodulator Unbalance	v_9, v_{11}, v_{13}	$V_3 = V_4 = 0$	—	—	0.8	V_{p-p}	16
Maximum Color Difference Output Voltage	v_{13}	$V_3 = V_4 = 0.6 V_{p-p}$	8.0	—	—		
	v_{11}		5.5	—	—		
	v_9		1.2	—	—		
Chroma Input Sensitivity	v_3	Adjust e_c for 5.0 v_{p-p} @ term No. 13 (B-Y)	—	0.2	0.35		
Relative R-Y Output	v_{11}		3.5	—	4.2		
Relative G-Y Output	v_9		0.75	—	1.25		
VDC Difference Between any two Output Terminals	$ V_9 - V_{11} $	$e_c = 0$	—	—	0.6	V	
	$ V_9 - V_{13} $						
	$ V_{11} - V_{13} $						
Input Impedance Reference Subcarrier Inputs	$r_{i6, 7}$		—	1.7	—	$k\Omega$	
	$c_{i6, 7}$		—	6	—	pF	
Input Impedance at Chroma Inputs	$r_{i3, 4}$		—	0.95	—	$k\Omega$	
	$c_{i3, 4}$		—	6	—	pF	
Output Resistance	$r_{o9, 10, 11, 13}$		—	180	—	Ω	

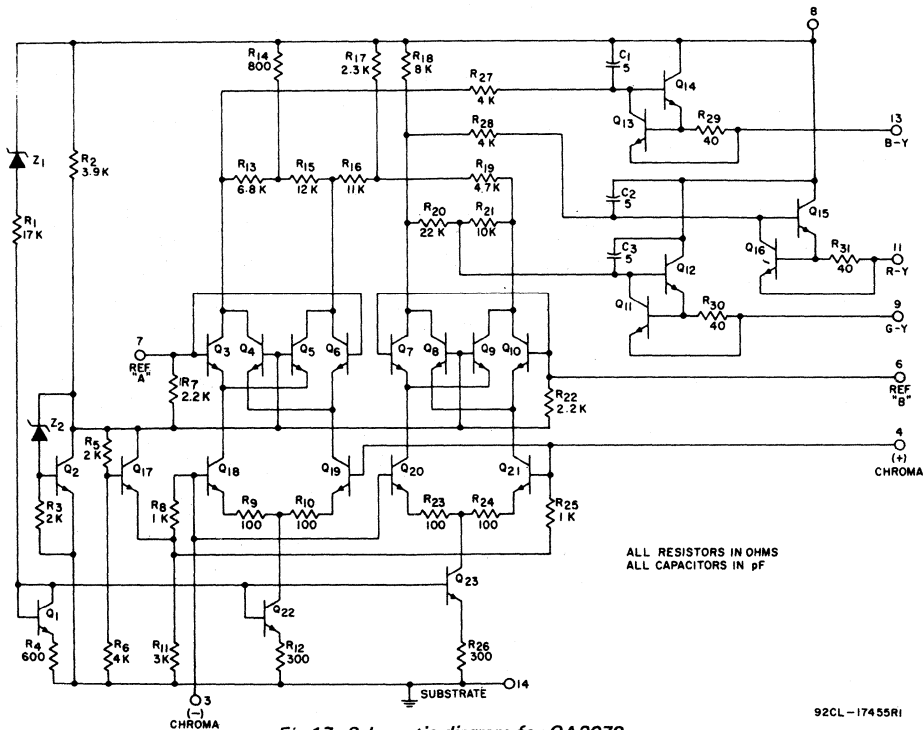


Fig. 17—Schematic diagram for CA3072.

CA3070, CA3071, CA3072 Types

The APC and ACC detectors are synchronous detectors which are keyed by the horizontal input pulse. This form of detection eliminates the need for a burst separator as an individual amplifier stage. When a positive pulse is present at terminal No. 4, the oscillator output is cutoff and the oscillator drive signal is diverted to the APC and ACC detectors. Referring to Fig. 3, the APC detector (Q_9 & Q_{10}) and the ACC detector (Q_5 & Q_6) are emitter driven from the oscillator transistor (Q_{17}), when the oscillator output amplifier transistors (Q_2 & Q_3) are cutoff. The chroma signal is applied to terminal Nos. 13 and 14. There is oscillator current drive to the APC and ACC detectors during the keying interval; burst separation is effectively accomplished by the gating action of the detectors. A further advantage of the keying action is the high gain made possible as a result of the low average current flow of the APC and ACC detectors. High resistor values of 62 kilohms at the detector output terminals provide proper detector bias consistent with the duty factor of the keying pulse. For a wider keying pulse, it is necessary that smaller values of detector load resistors be used.

In the absence of the keying pulse (line period), the resistor, R_{20} , biases the oscillator's output amplifier transistors (Q_2 & Q_3) on by keeping their emitters at a higher potential than the base bias voltages of Q_5 , Q_6 , Q_9 , and Q_{10} . The 3.58 MHz signal is now present at terminal Nos. 2 & 3. Photographs of oscilloscope traces for one line period at the terminal Nos. 1, 2, and 3 are shown in Fig. 19. The effect of the keying pulse is shown in Fig. 19a, and the cutoff of the oscillator output amplifier is shown in Fig. 19b and 19c.

The oscillator section of the CA3070 consists of the loop formed by Q_{18} and the emitter driven differential pair, Q_{13} & Q_{14} . The signal output from terminal Nos. 7 & 8 is coupled through the series tuned crystal circuit back through terminal No. 6 to Q_{16} & Q_{17} . The collector of Q_{17} drives the oscillator output amplifier and the APC & ACC detectors. Q_{17} is emitter coupled to transistor Q_{18} . The oscillator frequency and phase control is accomplished by the differential drive from the APC detector to transistors Q_{12} & Q_{15} which control the balance of Q_{13} & Q_{14} . The resulting phase of the feedback loop is determined by the relative amplitudes of the oscillator output signal at terminal Nos. 7 and 8. The 65 pF capacitor between terminal No. 7 and 8 provides the phase shifting component as the balance of Q_{13} and Q_{14} is varied. In this way the APC detector controls the crystal frequency at which the phase shift is cancelled in the feedback loop.

The controls for the CA3070 subcarrier regenerator circuit are the APC balance, the ACC balance, and the hue control. The hue control is a dc balance adjustment of the oscillator output amplifier transistors Q_2 & Q_3 . A phase delay network between the output terminals Nos. 2 & 3 determines the range of the hue control, which for the value shown in Fig. 18, is approximately 90° .

The ACC adjustment sets the initial balance of the ACC drive to the input of the CA3071 in Fig. 18 (terminal Nos. 1 and

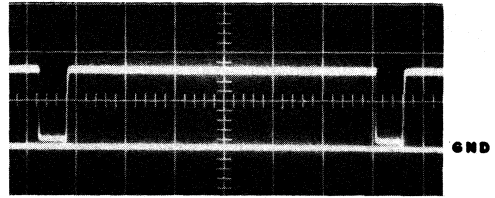


Fig. 19(a) - CA3070 terminal No. 1
7.5 V oscillator "gate off" pulse.

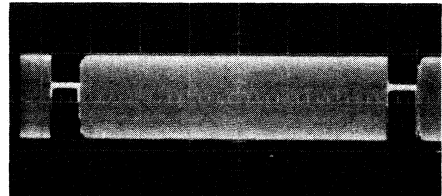


Fig. 19(b) - CA3070 terminal No. 2, 3.5 V_{p-p} oscillator output; one horizontal line, (gated off during burst).

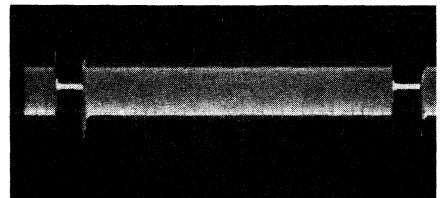


Fig. 19(c) - CA3070 terminal No. 3, 2.0 V_{p-p} oscillator output; one horizontal line, (gated off during burst).

14 of the CA3071). The APC is a frequency adjustment of the oscillator through the balance control of the APC detector.

As a setup adjustment, for both the ACC and APC, switch S1 is opened and S2 is closed. The chroma input to the system is removed and the dc voltage at terminal No. 6 of the CA3071 is noted. The switch S2 is then opened and the ACC adjusted to set the voltage at terminal No. 6 to that previously noted. Alternatively, the differential dc voltage at terminal Nos. 15 & 16 of the CA3070 may be set to 0 mV (± 2 mV) when S1 and S2 are open, and the CA3071 is removed from the circuit.

With the chroma signal still removed, the APC adjustment sets the frequency of the oscillator to 3.579545 MHz. Due to the gated off interval, a counter will not accurately record the frequency at the oscillator output amplifier terminals. Two simple and accurate methods are as follows: (1) a buffered crystal filter circuit, connected to the oscillator output amplifier terminals will continue to ring and fill the gated off window providing the proper interface to a counter; (2) the other method involves monitoring the demodulated output at the color difference output terminals

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CA3070, CA3071, CA3072 Types

of the CA3072. A zero beat signal, at the color difference outputs may be seen on an oscilloscope.

When these adjustments are made, similar oscilloscope traces should be seen as shown in Fig. 20.

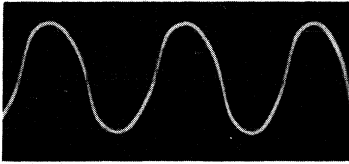


Fig. 20(a) - CA3070 terminal No. 6, oscillator waveform 1.1 V_{p-p} 3.58 MHz.

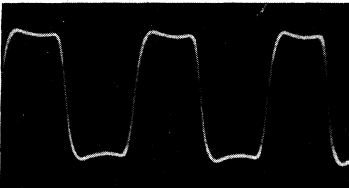


Fig. 20(b) - CA3070 terminal No. 7, oscillator waveform 1.4 V_{p-p} 3.58 MHz.

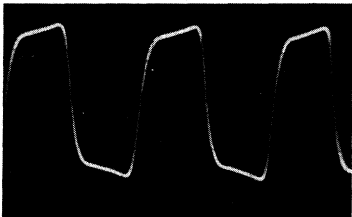


Fig. 20(c) - CA3070 terminal No. 8, oscillator waveform 1.6 V_{p-p} 3.58 MHz.

CA3071 CIRCUIT OPERATION

The CA3071 is the basic amplifier and control circuit of the chroma system. It contains the gain control functions of the ACC loop, the color killer, and the dc chroma gain control. The CA3071 is a wide band amplifier having two stages of voltage gain. Curves of frequency-response and linearity are shown in Figs. 12 & 13 for the wideband circuits shown in Fig. 11. This is the same basic amplifier as the one in the system shown in Fig. 18 except for the omission of the tuned circuits and the ACC loop connection. The amplifiers have bandwidths of greater than 10 MHz, and are usable well beyond 30 MHz. The signal swing of the wide band amplifier is in excess of 5 V_{p-p} , even with the typical load coupling as shown in Fig. 18. Fig. 21 (a, b and c) show the oscilloscope traces for an NTSC signal at the chroma input. The overall frequency-response curves are shown in Fig. 22.

CA3071 operation is as follows (Refer to Figs. 10 & 18). The input chroma signal is applied to terminal No. 2. This signal is amplified in a cascode differential circuit from Q₁₀ to Q₁₂

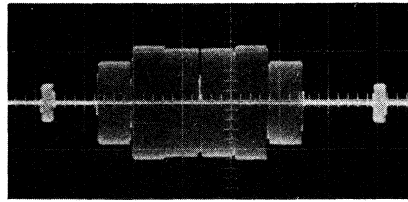


Fig. 21(a) - CA3071 chroma input 1.25 V_{p-p} ; one horizontal line of NTSC input signal.

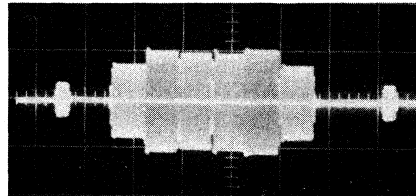


Fig. 21(b) - CA3071 terminal No. 6, amplifier No. 1 chroma output 2.3 V_{p-p} ; one horizontal line for 1.25 V_{p-p} chroma input

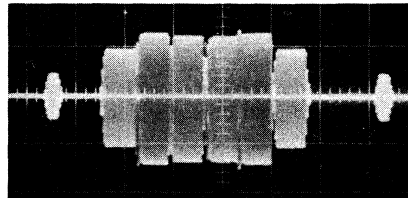


Fig. 21(c) - CA3071 terminal No. 9, amplifier No. 2 chroma output 5.5 V_{p-p} ; one horizontal line for 1.25 V_{p-p} chroma input

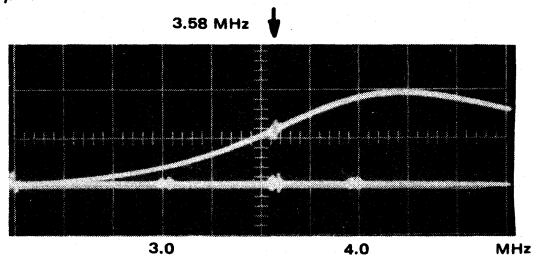


Fig. 22(a) - Frequency response sweep curve between terminal Nos. 2 & 6 for CA3071. $f = 250$ KHz/div.

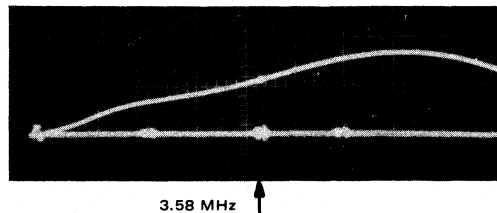


Fig. 22(b) - Frequency response sweep curve between terminal No. 2 of CA3071 and terminal No. 3 of CA3072. $f = 250$ KHz/div.

CA3070, CA3071, CA3072 Types

and the output is an emitter follower, Q14 (Terminal No. 6.) The signal is divided in the Q9 & Q12 differential amplifier, depending on the applied ACC error signal amplitude at terminal Nos. 1 & 14. The ACC error signal is derived from terminal Nos. 15 & 16 of the CA3070 and after filtering, is applied to terminal Nos. 1 & 14 of the CA3071.

At low signal drive, the 390 kilohm resistor at switch S1 (normally closed) unbalances the differential amplifier for high signal gain through Q12. As the burst level at the chroma input increases, the ACC drive changes differentially in a positive direction at terminal No. 14 and a negative direction at terminal No. 1. At strong signal levels the gain is reduced by diverting the balance of ac current in the differential amplifier from Q12 to Q9, which is shunted to ac ground at terminal Nos. 12 and 13. The ACC loop is completed through the chroma signal at terminal No. 6 of the CA3071 to terminal No. 14 (input) of the CA3070. A typical ACC characteristic is shown in Fig. 23.

The chroma signal is buffer connected from terminal No. 6 to terminal No. 7 of the CA3071 and is amplified in the 2nd

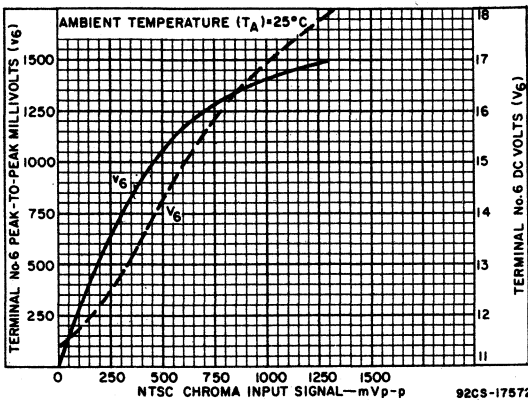


Fig. 23 - Typical ACC characteristics for chroma system of Fig. 18

stage of voltage gain. Both the color killer adjustment and the dc chroma gain control are applied to the 2nd stage to control the chroma output at terminal No. 9. The color killer section of the CA3071 is a Schmitt trigger & amplifier circuit consisting of transistors Q1, Q2 and Q3. Under maximum chroma output conditions, the diode D2 is reversed biased, and the signal path is through Q15, Q4 and Q5 to terminal No. 9. When the color killer circuit is actuated, or the chroma gain control is adjusted to a higher positive voltage at terminal No. 10, the anode voltage of diode D2 is increased to draw current from the signal path at the emitter of Q4. This decreases the chroma gain as the potential at terminal No. 10 is increased. When the potential at terminal No. 10 is the same as terminal No. 8, the chroma output at terminal 9 is cutoff.

The color killer circuit provides an abrupt voltage swing at the anode of D2 to cutoff the chroma output when the Schmitt trigger circuit is forward biased at terminal No. 13. In the circuit of Fig. 18, the color killer adjustment is a resistance divider circuit which establishes the threshold of burst level at which the killer operates the chroma amplifier.

CA3072 CIRCUIT OPERATION

The CA3072 is a chroma demodulator having full color difference signal demodulation capability. The chroma signal is applied to terminal Nos. 3 & 4 and the reference subcarrier signal is applied to terminals Nos. 6 & 7 of the CA3072. The output color difference signals are B-Y at terminal No. 13, R-Y at terminal No. 11, and G-Y at terminal No. 9. The typical level of differential chroma drive required at terminal Nos. 3 & 4 is 400 mVp-p. The amplitude of chroma at terminal No. 6 & 7 is approximately 1.0 volt at 104° relative phase difference which results in a B-Y output amplitude of 5Vp-p. The voltages of the R-Y & G-Y outputs are at 3.8 and 1.0 Vp-p respectively, when there is 5Vp-p output at B-Y. These comparative signals are based upon a complete phase rotation of the chroma relative to the subcarrier signal reference. The relative demodulation phase and amplitude ratios of the Fig. 18 circuit are shown in the oscilloscope trace photographs of Fig. 24. Using the hue control setting for B-Y phase at the B-Y output, the G-Y color-difference signal is approximately -104° and the R-Y color-difference signal is approximately +106°. Since the amplitude ratios are a function of the applied signal phase relationship, the NTSC color difference output signals are shown here primarily for phase reference conditions.

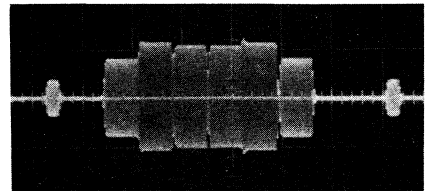


Fig. 24(a) - CA3072 - terminal No. 3 or 4, chroma input signal, 220 mVp-p, one horizontal line

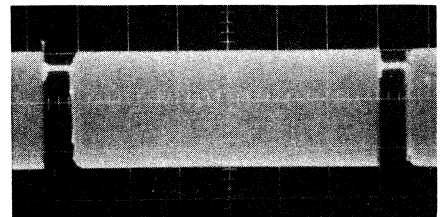


Fig. 24(b) - CA3072 - terminal No. 6 or 7, reference subcarrier 1.2 Vp-p, one horizontal line

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CA3070, CA3071, CA3072 Types

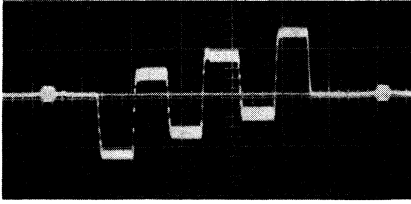


Fig. 24(c) - CA3072 terminal No. 13, 4.8 v_{p-p} B-Y output, one horizontal line

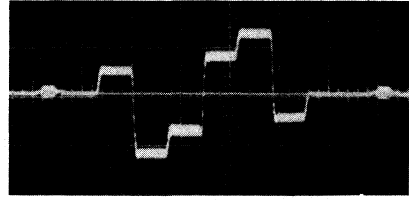


Fig. 24(e) - CA3072 - terminal No. 11, 5.2 v_{p-p} R-Y output, one horizontal line

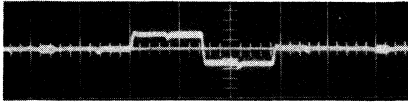


Fig. 24(d) - CA3072 - terminal No. 9, 1.2 v_{p-p} G-Y output, one horizontal line

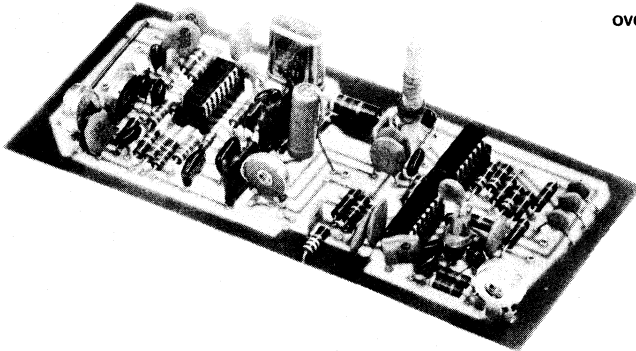


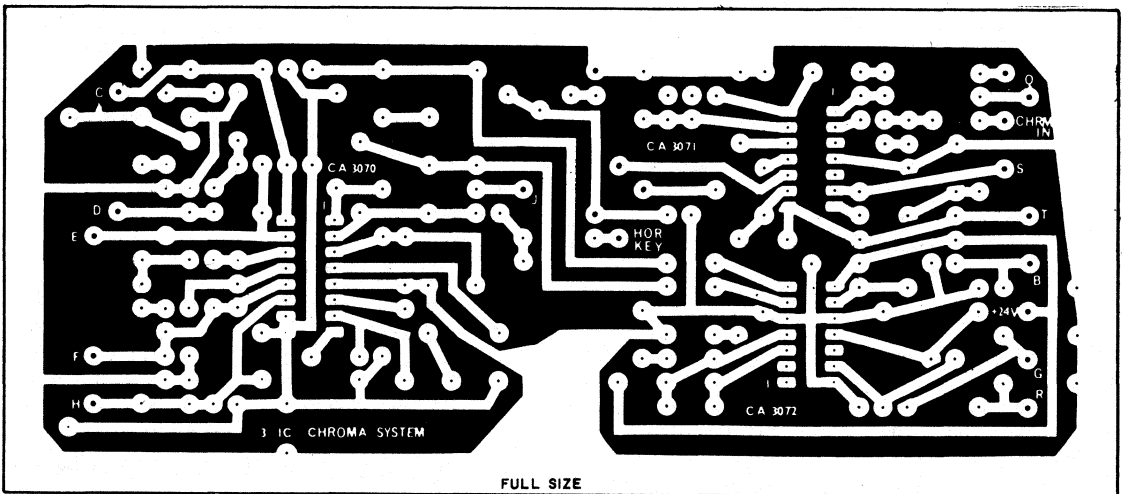
Fig. 25 (a) - Circuit layout and template (printed circuit board) for TV chroma system CA3070, CA3071, and CA3072.

CHROMA SYSTEM CONSTRUCTION

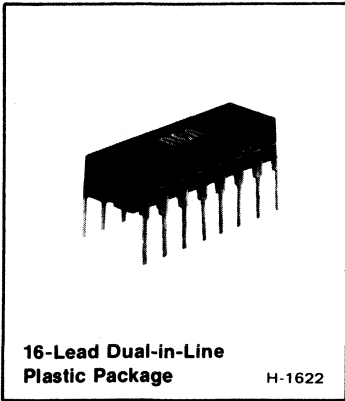
Fig. 25 shows the complete CA3070, CA3071 and CA3072 chroma system in the Fig. 18 circuit. Table I lists the dc terminal voltages for the system. The chroma gain and hue controls, as well as the switches S1 and S2 are removed. The template circuit board layout is also shown for duplication purposes. It should be noted that a few component values are modified in Fig. 18 from the dynamic circuit values of the data sheet. These are necessary for system matching and overall filter requirements.

TABLE I TYPICAL CHROMA SYSTEM TERMINAL DC VOLTAGES (NO SIGNAL INPUT)

TERMINAL No.	DC VOLTS		
	CA3070	CA3071	CA3072
1	7.6	7.3	—
2	11.5	1.7	—
3	11.5	—	3.3
4	-1.7	0	3.3
5	0	—	—
6	2.8	11.4	5.9
7	11.2	1.4	5.9
8	11.2	23.0	24.0
9	—	VARIABLE	14.7
10	12.0	VARIABLE	—
11	7.8	VARIABLE	14.7
12	7.8	15.0	—
13	6.7	VARIABLE	14.7
14	6.7	7.1	0
15	7.3	—	—
16	7.1	—	—



(b) - Printed circuit board template (same size).



TV Chroma Amplifier/ Demodulator

Provides Complete System for Processing Chroma
When Used with RCA-CA3070 or CA3170

FEATURES:

- Excellent linearity in dc chroma gain-control circuit
- Improved filtering resulting in reduced 7.2 MHz output from the color demodulators
- Current limiting for short-circuit protection
- Good tolerance to B+ supply variations
- Good temperature coefficient stability

The RCA-CA3121E is a monolithic silicon integrated circuit chroma amplifier/demodulator with ACC and killer control for color-TV receivers. It is designed to function compatibly with the CA3070 or CA3170 in a two-package chroma system. Figs. 5 and 6 show a functional block diagram and the outboard circuitry of a typical two-package chroma

system incorporating the CA3121E and CA3170, respectively.

The CA3121E is supplied in a 16-lead dual-in-line plastic package.

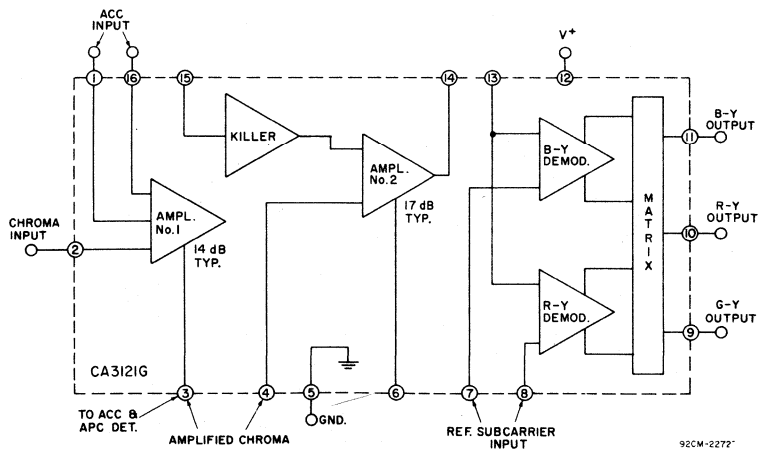


Fig. 1 — Functional block diagram of the CA3121E.

Linear Integrated Circuits

CA3121E

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

Supply Voltage	30 V
Device Dissipation:	
Up to $T_A = 55^\circ\text{C}$	1 W
Above $T_A = 55^\circ\text{C}$	derate linearly 10.5 mW/ $^\circ\text{C}$
Operating Temperature Range	-40 to +85 $^\circ\text{C}$
Storage Temperature Range	-65 to +150 $^\circ\text{C}$
Lead Temperature (During Soldering)	
At distance 1/16" \pm 1/32" (1.59 \pm 0.79 mm) from case for 10 s max.	+265 $^\circ\text{C}$

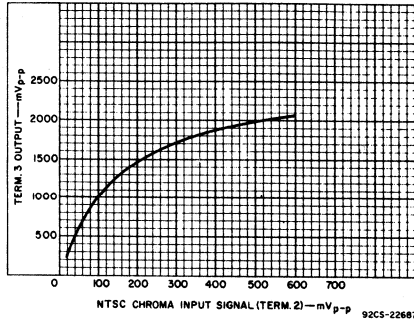


Fig. 2 — Typical ACC plot for the CA3121E when used with the CA3070.

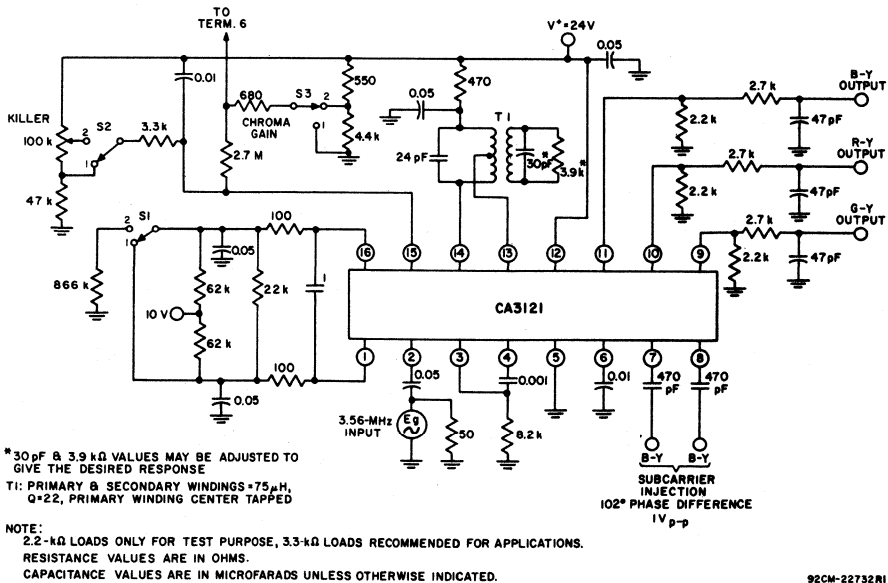


Fig. 3 — Typical characteristics test circuit for the CA3121E.

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$ and Reference to Test Circuit (Fig. 3)

CHARACTERISTIC, TERMINAL MEASURED, AND SYMBOL	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
Supply Current I_T	—	—	40	50	mA
Input Sensitivity V_2	Vary E_g ; set V_4 for 55 mV RMS	6	10	15	mV RMS
Second-Stage Sensitivity V_4	Vary E_g ; set V_{11} for 2 V RMS	25	55	100	mV RMS
Output Voltage (Killer off) V_{11}	Switch Position: S1=2, S2=2, S3=2 Adjust killer potentiometer until output drops	—	—	70	mV RMS
Demodulator Characteristics:					
Output Voltages V_g, V_{10}, V_{11}	—	13	14.3	15.6	V
DC Output Balance (Between any 2 outputs)	—	-0.6	—	+0.6	V
Unbalance V_g, V_{10}, V_{11}	$E_g=0$; Switch Position: S1=1, S2=1, S3=1	—	—	0.8	Vp-p
Relative Outputs— R-Y V_{10}	Vary E_g ; set V_{11} for 2 V RMS	1.4	1.52	1.68	V RMS
G-Y V_9		0.3	0.4	0.5	V RMS
Relative Phase— R-Y V_{10}	Vary E_g ; set V_{11} for 2 V RMS; read phase of V_{10} and V_g with V_{11} as reference	-101	-106	-111	degrees
G-Y V_9		112	104	96	degrees
Max. Output Voltage V_{11}	$E_g = 750$ mV	2.8	—	—	V RMS

CIRCUIT OPERATION

The CA3121E consists of three basic circuit sections: (1) amplifier No.1, (2) amplifier No.2, and (3) demodulator. Amplifier No.1 contains the circuitry for automatic chroma control (ACC) and color-killer sensing. The output of amplifier No.1 (Terminal 3) is coupled to the Chroma Signal Processor (CA3070, CA3170 or equivalent) for ACC and automatic phase control (APC) operation and to the input of amplifier No.2 (Terminal 4) containing the chroma gain control circuitry. The signal from the color-killer circuit in amplifier No.1 acts upon amplifier No.2 to greatly reduce its gain.

The output from amplifier No.2 (Terminal 14) is applied, through a filtering network, to the demodulator input (Terminal 13).

The demodulator also receives the R-Y and B-Y demodulation subcarrier signals (Terminals 7 and 8) from the oscillator output of the Chroma Signal Processor. The R-Y and B-Y demodulators and the matrix network contained in the demodulator section of the CA3121E reconstruct the G-Y signal to achieve the R-Y, G-Y, and B-Y color difference signals. These high-level outputs signals with low impedance outputs are suitable for driving high-level R, G, and B output amplifiers. Internal capacitors are included on each output to filter out unwanted harmonics. For additional operating information and signal waveforms, refer to Television Chroma System (utilizing RCA-CA3070, CA3071, CA3072), File No. 468.

CA3121E

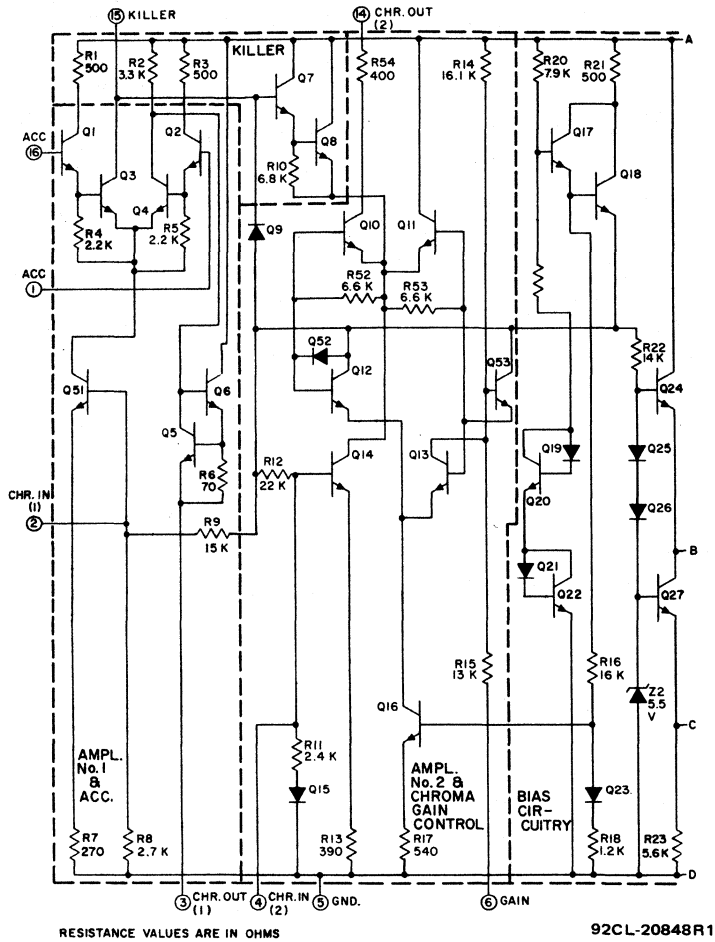


Fig. 4 - Schematic diagram of the CA3121E (cont'd on next page).

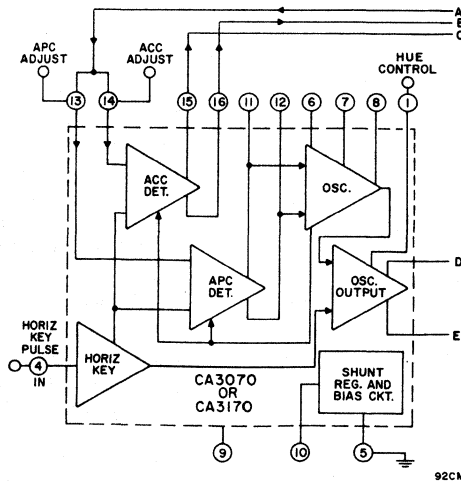


Fig. 5 - Simplified functional diagram of a two-package TV chroma system, utilizing the CA3121E and CA3070 or CA3170 (cont'd on next page).

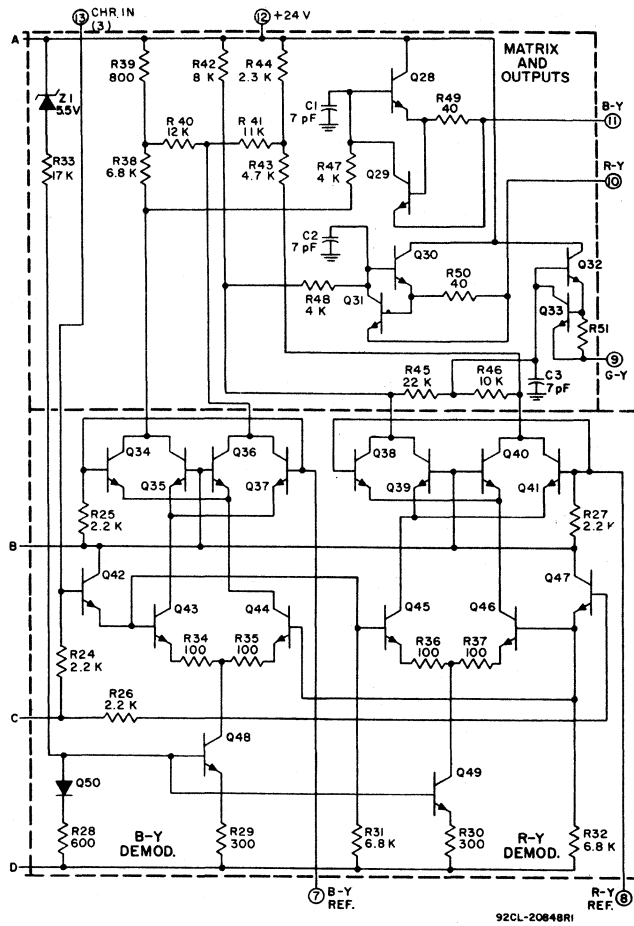


Fig. 4 - Schematic diagram of the CA3121E (cont'd from previous page).

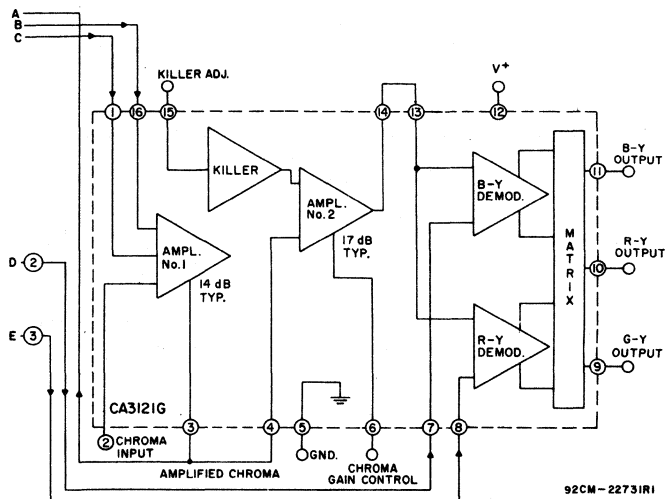
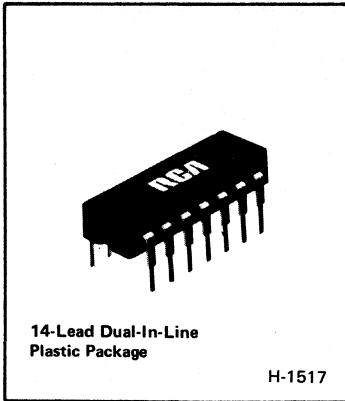


Fig. 5 - Simplified functional diagram of a two-package TV chroma system utilizing the CA3121E and CA3070 or CA3170 (cont'd from previous page).

Television Chroma Demodulator



Features:

- Luminance input
- Blanking control input
- Three separate demodulators with independent phase control
- Low output offset voltage 0.4 V

RCA-CA3125E is a monolithic silicon integrated-circuit chroma demodulator having three separate demodulators with independent phase control. It is designed to function compatibly with the CA1398E IC Chroma Processor as well as other commercially available Chroma Processors in R-G-B Systems of color-TV receivers. Fig. 2 shows a functional block diagram of a 2-package TV Chroma System incorporating the CA3125E and CA1398E. The CA3125E is supplied in a 14-lead dual-in-line plastic package.

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

SUPPLY VOLTAGE	25 V
SUPPLY CURRENT	20 mA
AMBIENT-TEMPERATURE RANGE:	
Operating	-40°C to $+85^\circ\text{C}$
Storage	-65°C to $+150^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance $1/16'' \pm 1/32''$ (1.59 ± 0.79 mm)	
from case for 10 s max.	265°C

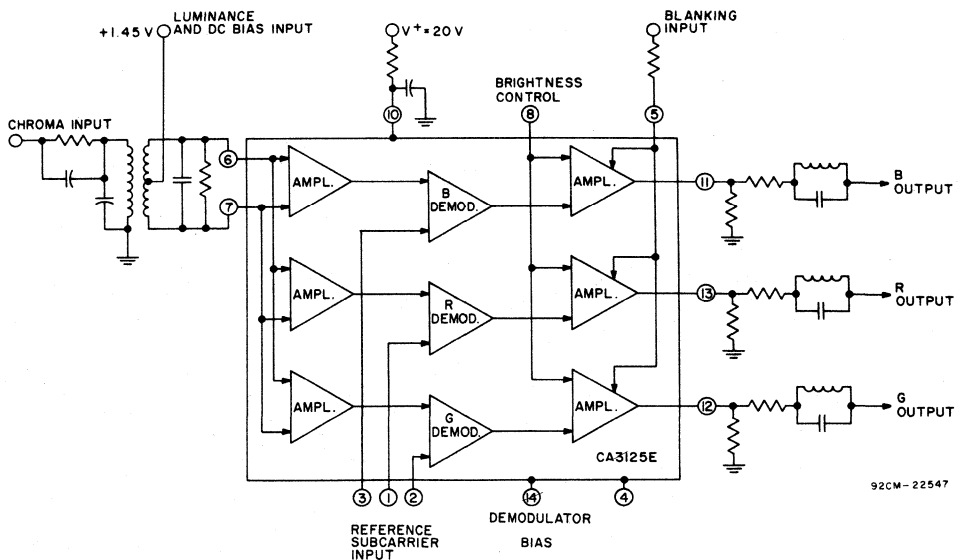


Fig. 1 - Functional block diagram of the CA3125E.

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CA3125E

**TYPICAL STATIC CHARACTERISTICS AT $T_A = 25^\circ\text{C}$,
 $V^+ = +20$ VOLTS**

SUPPLY CURRENT 9.6 mA

BRIGHTNESS CONTROL VOLTAGE:

Measured with 8 volts at

Terminals 11, 12, and 13 1.4 V

MAX. OUTPUT DIFFERENCE VOLTAGE:

Measured between any two of

Terminals 11, 12, and 13 ± 0.4 V

MAXIMUM DC DETECTOR UNBALANCE VOLTAGE:

DC voltage shift on Terminals 11, 12, and 13

when Terminals 1, 2, and 3 are alternately

biased 0.5 volt positive, then negative with

reference to Terminal 14 +150 mV

**TYPICAL DYNAMIC CHARACTERISTICS AT $T_A = 25^\circ\text{C}$,
 $V^+ = +20$ volts**

BLUE CHROMA GAIN:

Peak-to-peak voltage at Terminal 11 with 1.0 volt

peak-to-peak applied differentially between

Terminals 6 and 7, and with a subcarrier

injection voltage of 1 volt peak-to-peak

7.36 V_{p-p}

RED GAIN RATIO:

Peak-to-peak voltage at Terminal 13

Peak-to-peak voltage at Terminal 11

X 100 100%

GREEN GAIN RATIO:

Peak-to-peak voltage at Terminal 12

Peak-to-peak voltage at Terminal 11

X 100 30%

LUMINANCE GAIN:

Peak-to-peak voltage measured at Terminals 11,

12, and 13, with a peak-to-peak voltage of

0.1 volt applied to Terminals 6 and 7

(common mode), and with no subcarrier

injection 0.7 V_{p-p}

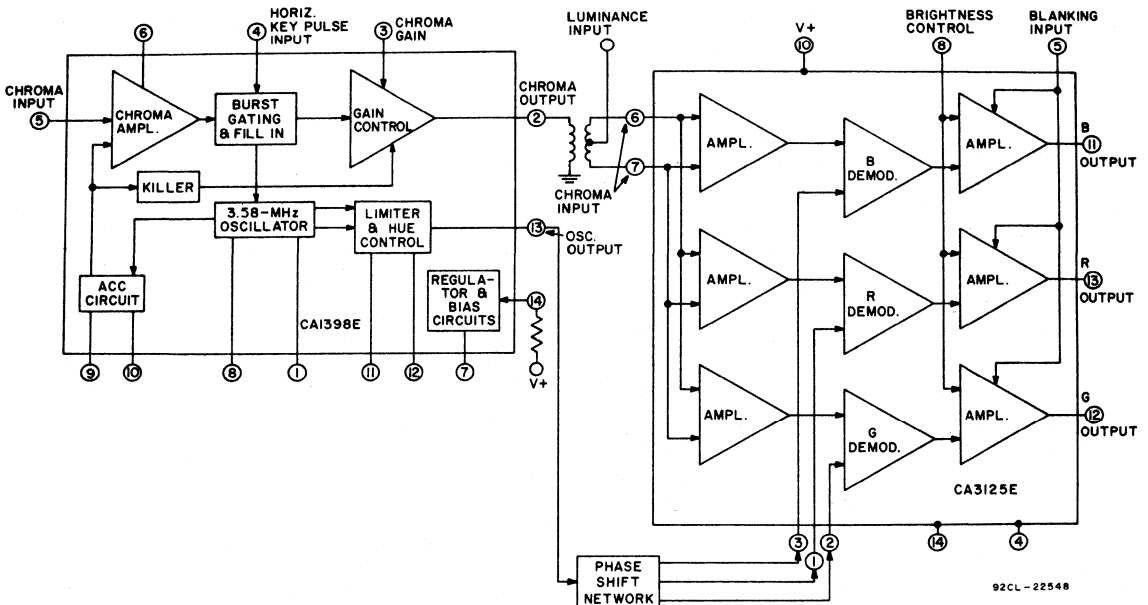
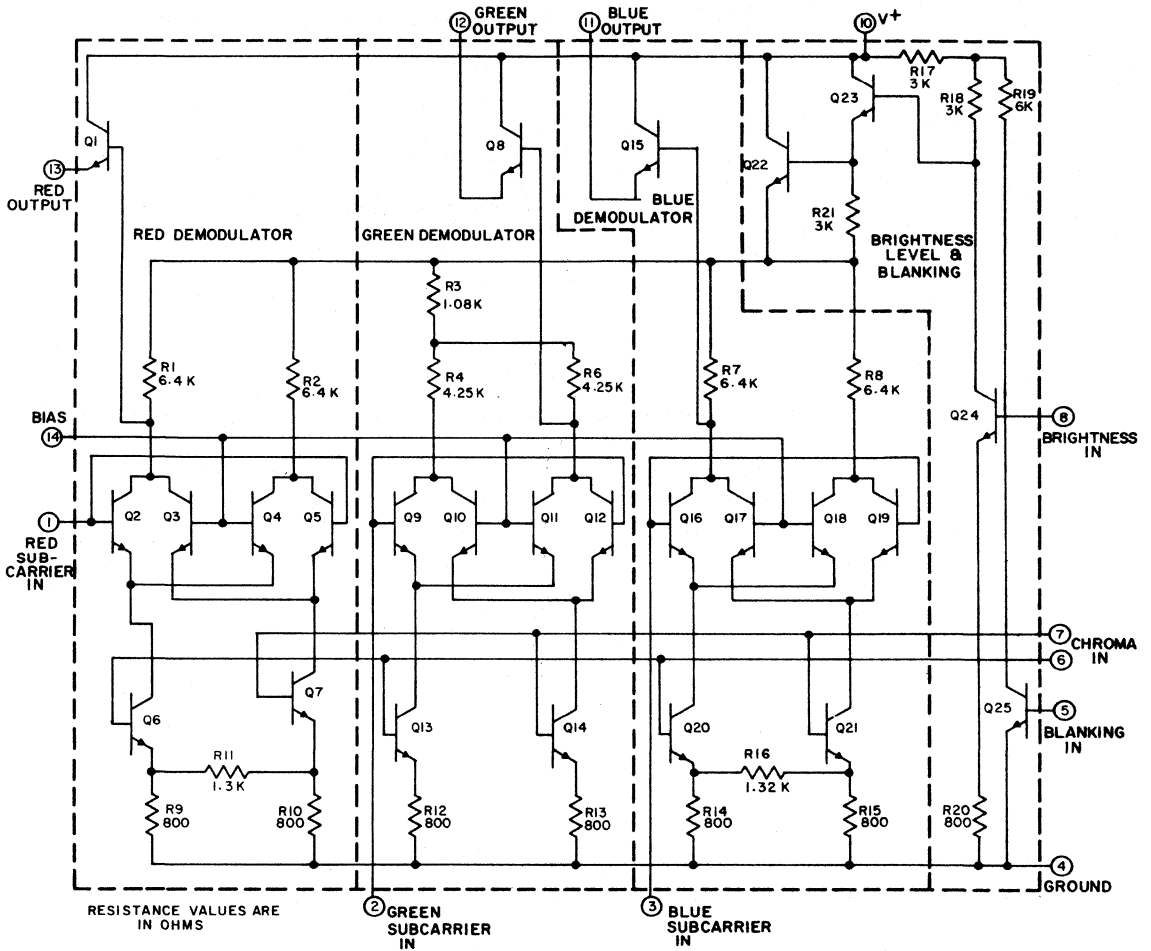


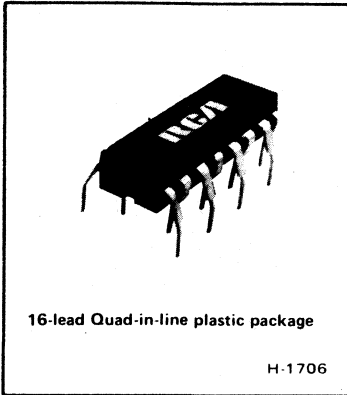
Fig. 2 - TV chroma system functional block diagram.



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Fig. 3 - Schematic diagram of the CA3125E.

CA3126Q



TV Chroma Processor

Features:

- Phase-locked subcarrier regeneration utilizes sample-and-hold techniques
- Automatic chrominance control (ACC)/killer detector employs sample-and-hold techniques
- Supplementary ACC with an overload detector to prevent oversaturation of the picture tube
- Sinusoidal subcarrier output
- Keyed chroma output
- Emitter-follower buffered outputs for low output impedance
- Linear dc saturation control
- Internal zener-regulated reference potentials

RCA-CA3126Q is a monolithic silicon integrated circuit designed for chroma processing applications in color TV receivers. It is compatible with the CA3067 chroma demodulator as well as other chroma demodulators.

- Only the initial crystal filter tuning is required. . . no killer or ACC adjustments required at any time
- Few external components required
- Compensation for temperature and supply variations
- All terminals protected against short circuits

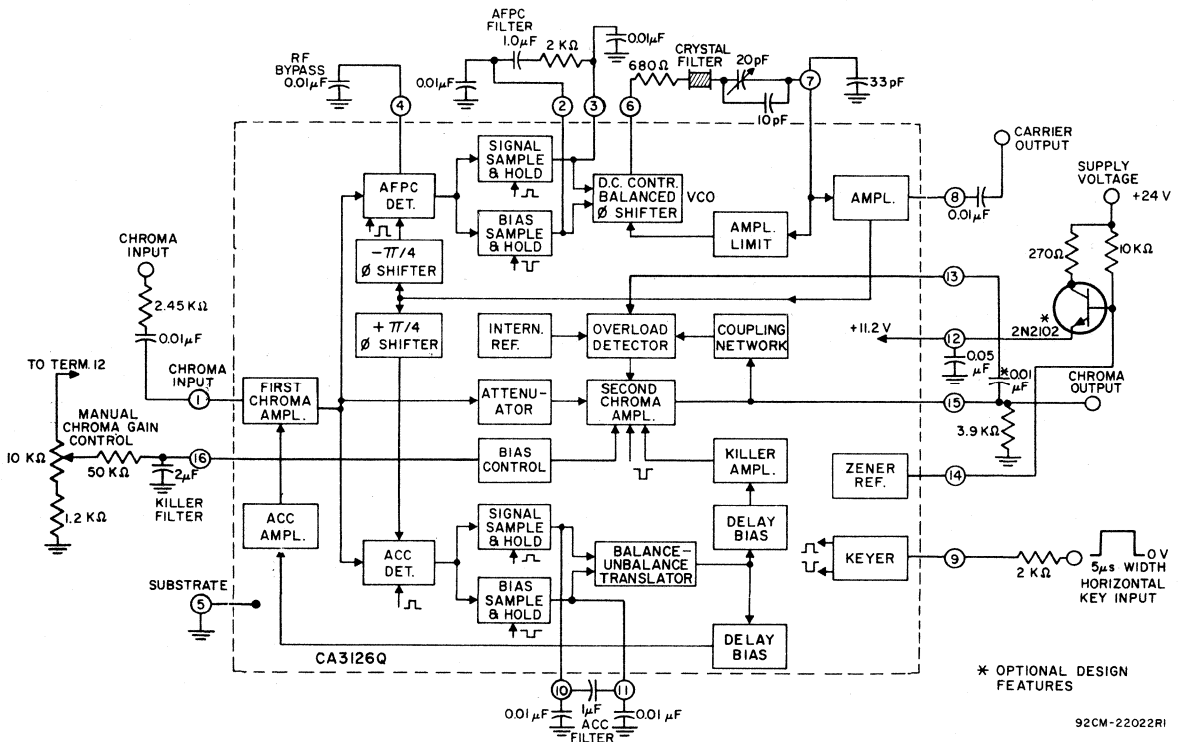


Fig. 1—Block diagram of CA3126Q TV Chroma Processor.

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

DEVICE DISSIPATION:

Up to $T_A = 55^\circ\text{C}$ 750 mW
Above $T_A = 55^\circ\text{C}$ derate linearly 7.9 mW/ $^\circ\text{C}$

DC SUPPLY VOLTAGE (Across Terms. 5 and 12)[▲] 13.2 V

DC CURRENT:

Into Term. 12 38 mA
Into Term. 14 20 mA

DC VOLTAGE (Terminal 9):

Negative Rating -5 V
Positive Rating 3 V

AMBIENT TEMPERATURE RANGE:

Operating -40 to +85 $^\circ\text{C}$
Storage -65 to +150 $^\circ\text{C}$

LEAD TEMPERATURE (During Soldering):

At a distance not less than 1/32 in. (0.79 mm)
from case for 10 seconds max. +265 $^\circ\text{C}$

[▲]This rating does not apply when using the internal zener reference in conjunction with an external pass transistor.

ELECTRICAL CHARACTERISTICS

Test Conditions: $T_A = 25^\circ\text{C}$, chroma control at maximum position for all characteristics tests except for chroma output test. For this test, control should be set at minimum position. Electrical characteristics referenced to test circuit,

CHARACTERISTIC	TERMINAL, MEASUREMENT, AND SYMBOL	SWITCH POS.		CHROMA INPUT TP1	LIMITS			UNITS
		S1	S2		Min.	Typ.	Max.	
Static Characteristics								
Voltage Regulator	V_{12}	2	2	0	10.1	11.2	12.1	V
Supply Current	I_{12}	2	2	0	16	25	38	mA
Dynamic Characteristics (See Note 1)								
Pull-in Range*	V_8	*	2	0.5 V_{p-p}	±250	—	—	Hz
Oscillator Output	V_8	2	2	0	0.6	1.0	—	V_{p-p}
100% Chroma Output	V_{15}	1	2	0.5 V_{p-p}	1.4	2.7	—	V_{p-p}
Overload Detector	V_{15}	1	1	0.5 V_{p-p}	0.4	—	0.7	V_{p-p}
Minimum Chroma Output	V_{15}	1	2	0.5 V_{p-p}	—	—	20	m V_{p-p}
200% Chroma Output	V_{15}	1	2	1 V_{p-p}	70	100	140	% of 100% reading
20% Chroma Output	V_{15}	1	2	0.1 V_{p-p}	40	—	105	
Kill Level	V_{TP1}	1	2	vary	5	—	60	m V_{p-p}

Note 1: Except for pull-in range testing, tune oscillator trimmer capacitor for free-running frequency of 3.579545 MHz ± 10 Hz.

*Set Switch 1 to Position 2, detune oscillator ± 250 Hz, set Switch 1 to Position 1, and check for oscillator pull-in.

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CA3126Q

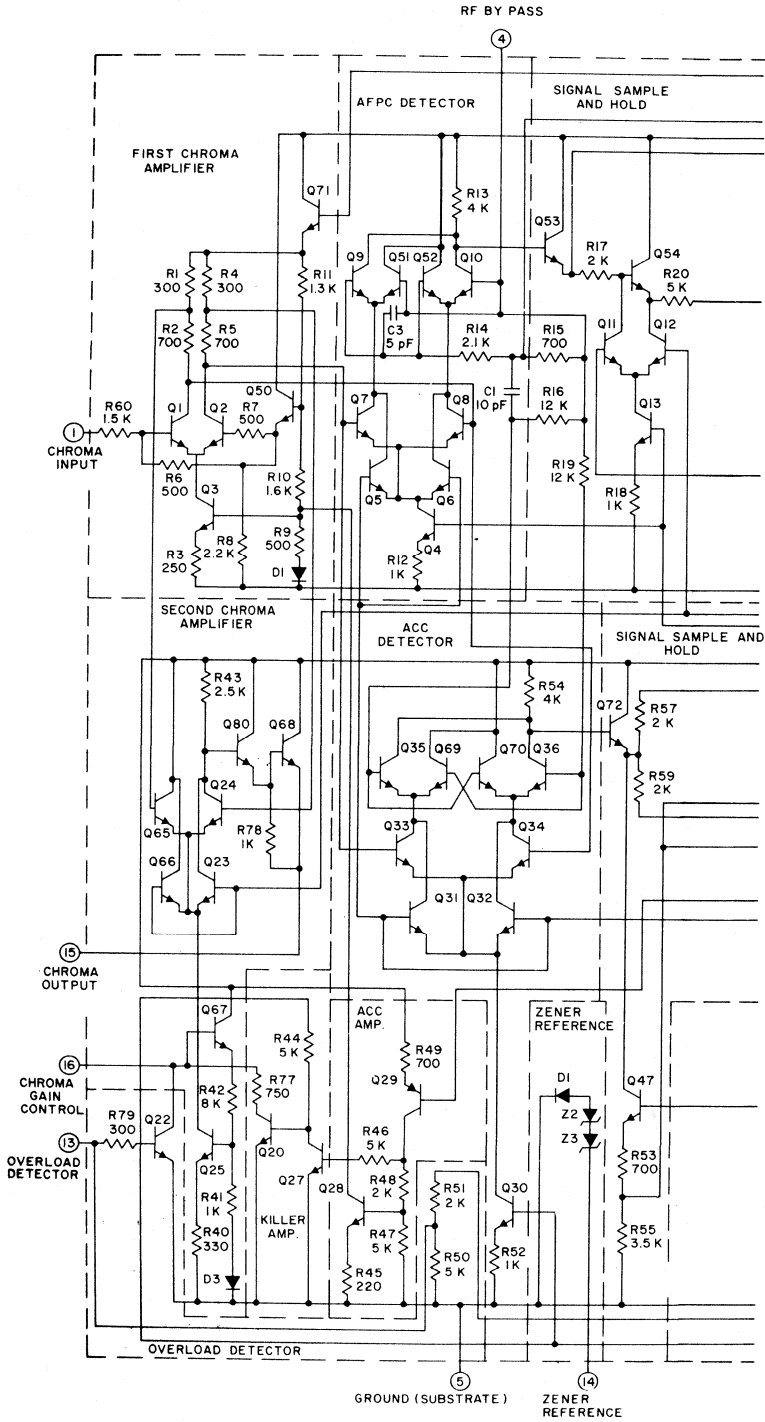


Fig. 2 - Schematic diagram of the CA3126Q.

TV/CATV Circuits

CA3126Q

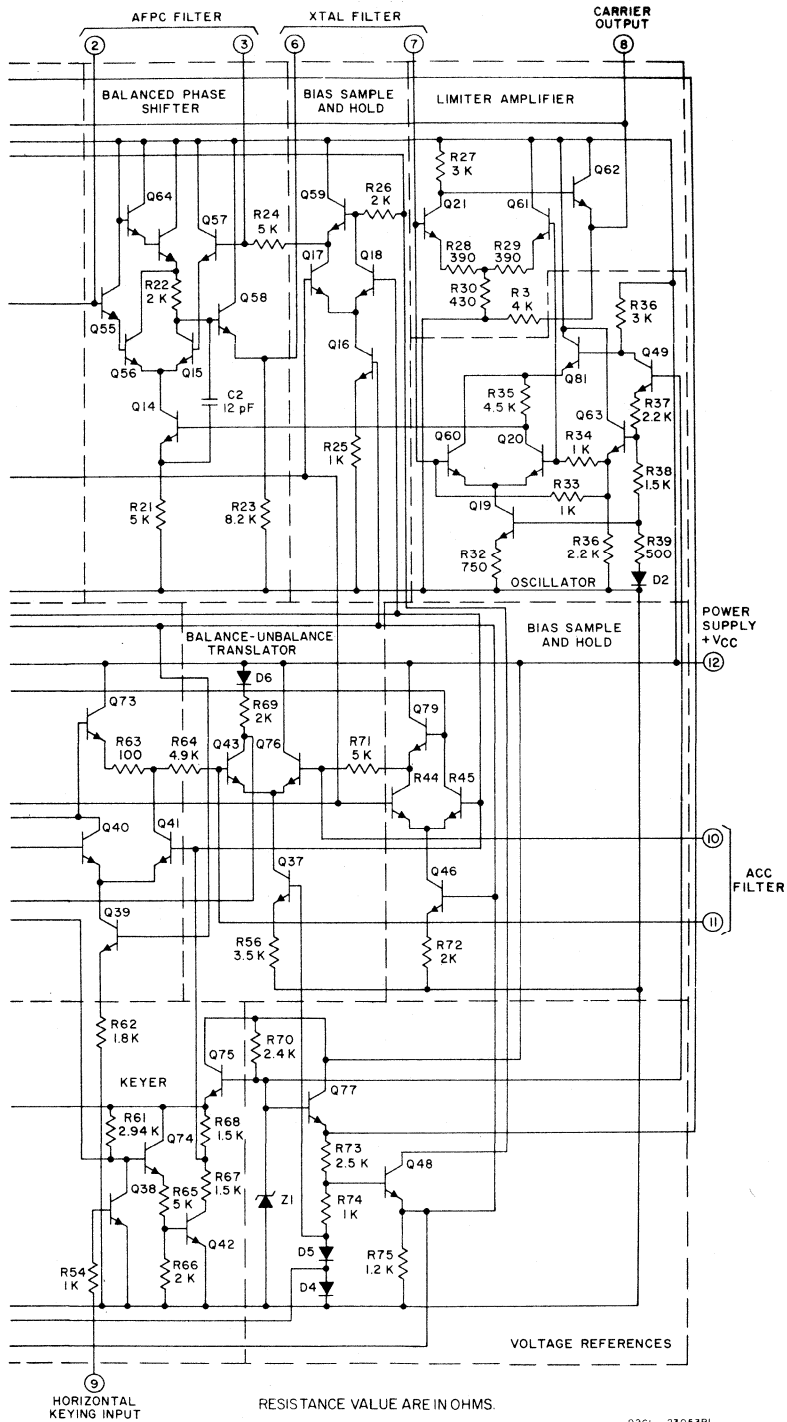


Fig. 2—Schematic diagram of the CA3126Q (cont'd).

CA3126Q

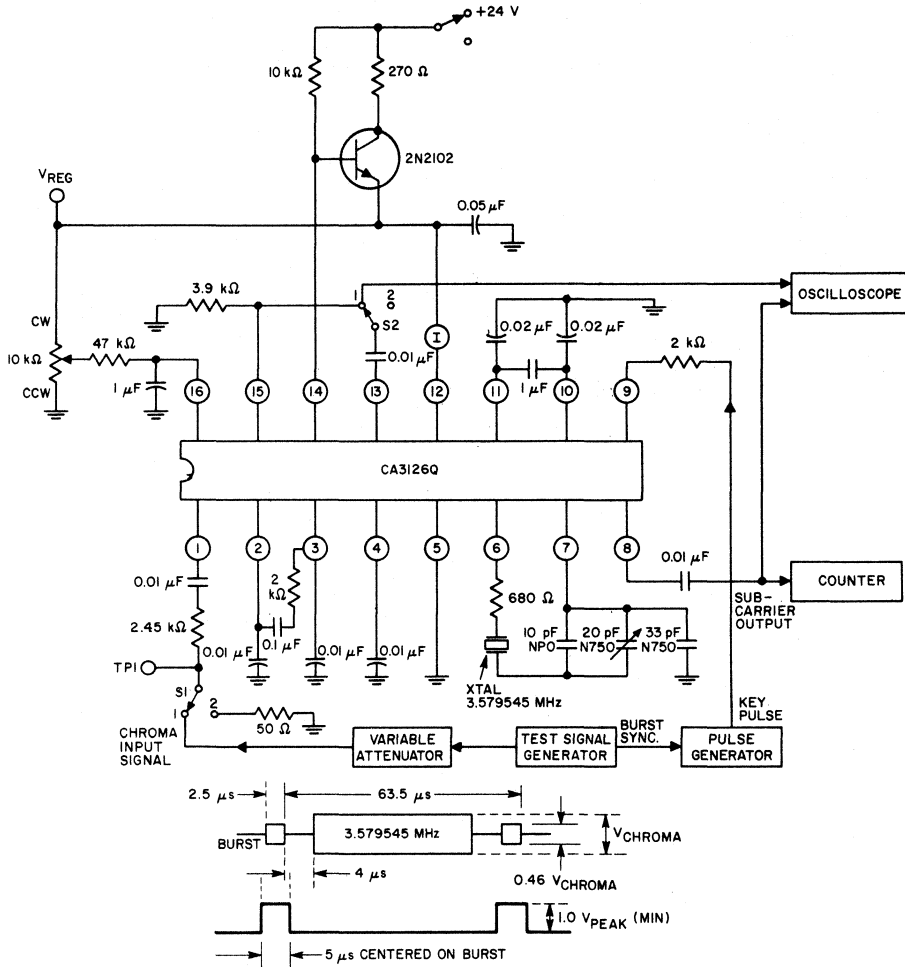


Fig. 3—Test circuit for CA3126Q.

CIRCUIT DESCRIPTION

The following paragraphs briefly describe the circuit operation of the CA3126Q (shown in Figs. 1 and 2). A detailed description of the operation of various portions of the CA3126Q is given in ICAN-6247, "Application of the CA3126Q Chroma-Processing IC Using Sample-and-Hold-Techniques".

The chroma input is applied to Terminal 1 through the desired band-shaping network. A 2,450-ohm resistor should be placed in series with Terminal 1 to minimize oscillator pickup in the first chroma amplifier. This amplifier supplies signals to the second chroma amplifier and to the ACC and AFPC detectors. The first chroma amplifier is gain-controlled by the ACC amplifier.

A horizontal keying pulse is applied to Terminal 9. This pulse must be present to ensure proper operation of the oscillator circuit. The subcarrier burst is sampled during the keying interval in the AFPC detector. The error voltage, produced at Terminal 2 and proportional to the burst phase, is compared to the quiescent bias voltage at Terminal 3 by the sample-and-hold circuitry. This "compared" voltage controls the phase-shifting network in the phase-locked loop. The operation of the AFPC loop is independent of any external adjustments or voltages except for an initial capacitor adjustment to set the free-running frequency.

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The regenerated oscillator signal at Terminal 8 is applied internally to the AFPC and ACC detectors through +45- and -45-degree phase-shifter networks to establish the proper phase relationship for these detectors. The ACC detector, which also samples the burst during the keying interval, produces a correction voltage proportional to the burst amplitude. The correction voltage is compared to the quiescent bias level using sample-and-hold circuitry similar to that used in the AFPC portion of the circuit. The "compared" voltage is applied internally to the ACC amplifier and killer amplifier. Because the amplifier gains and killer threshold are determined by the ratios of the internal resistors, these functions are independent of external voltages or controls.

The attenuated chroma signal is fed to the second chroma amplifier, where the burst is removed by keyer action. The killer amplifier, the chroma gain control, and the overload detector control the action of the second chroma amplifier, whose gain is proportional to the dc voltage at Terminal 16. The overload detector (Terminal 13) receives a sample of the chroma output (Terminal 15) and detects the peak of the signal. The detected voltage is stored in an external capacitor connected to Terminal 16. This stored voltage on Terminal 16 affects the gain of the second chroma in the same manner as the chroma gain control.

APPLICATIONS INFORMATION

General Considerations

The block diagram shown in Fig. 1 is typical of the type of circuit used in the practical application of the CA3126Q. Several items are critical for proper operation of the circuit.

1. A series resistor of approximately 2,450 ohms (or high source impedance) must be used at the chroma input, Terminal 1. This high impedance minimizes pickup of unbalanced currents, particularly of the subcarrier oscillator signal.
2. When the overload detector is used, a large resistor (nominally 47,000 ohms) must be placed in series with Terminal 16 to set the required RC time constant. The same RC network series serves to set the killer time constant.
3. The setting of the free-running oscillator frequency requires the presence of the keying pulse. The free-running frequency will be erroneous if Terminal 1 is dc shorted during the setting operation because of the dc offset voltage introduced to the AFPC detector.
4. Care must be taken in PC board designs to provide reasonable isolation between the oscillator portion of the circuit (Terminals 6, 7, and 8) and the chroma input (Terminal 1).

Overload Detector

The overload detector accomplishes two purposes:

1. It prevents oversaturation due to low burst-to-chroma ratios.
2. It prevents overload conditions due to noise.

Both of these conditions are discussed in more detail in ICAN-6247. The extent to which the overload detector is used depends upon the individual receiver design goals. If greater than 0.5-volt peak-to-peak output is desired, the chroma output at Terminal 15 can be tapped to yield any desired degree of overload detector action.

Chroma Gain Control

The chroma gain control operates by varying the base bias on current source transistor Q25. To ensure proper temperature tracking of the chroma gain control, it is essential that the control be operated from a supply source derived from the reference voltage at Terminal 12. Because the control operates from a current source, chroma gain is much more predictable and far less temperature sensitive than controls that steer current by means of a differential amplifier. The typical chroma gain characteristic for the CA3126Q is shown in Fig. 4.

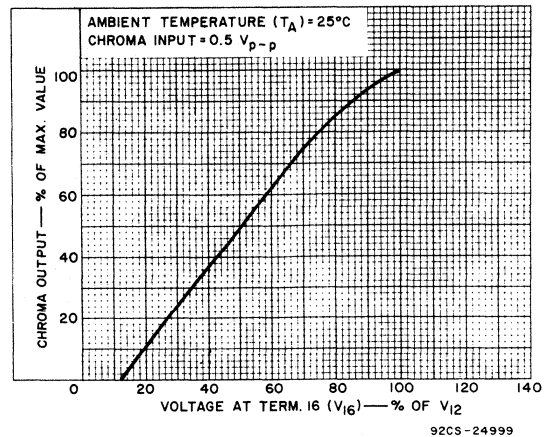


Fig. 4—Chroma gain control.

Subcarrier Regenerator Oscillator

The oscillator filter consists of a 3.579545-MHz crystal, a 680-ohm resistor, and a 10-pF capacitor connected in series across Terminals 6 and 7. A 33-pF capacitor, shunt connected from Terminal 7 to ground, rolls off higher-order harmonics, thereby preventing oscillation at the crystal third-harmonic frequency. A curve of the typical static phase error as a function of the free-running oscillator frequency is shown in Fig. 5. It should be noted that the slope of the curve determines the dc gain of the phase-locked loop, i.e., 40 Hz per degree.

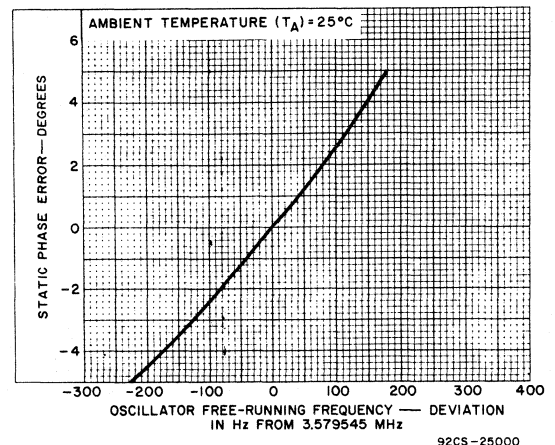


Fig. 5—Static phase error.

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CA3126Q

Thermal Considerations

The circuit of the CA3126Q is thermally compensated to achieve the optimal operating characteristics over the normal operating temperature range of TV receivers. Figs. 6 and 7 show the oscillator- and chroma-output amplitudes and phases as a function of temperature (Terminals 8 and 15), respectively.

Both the oscillator- and chroma-output amplitudes and phases are measured relative to the chroma-input phase. The performance of the oscillator free-running frequency as a function of temperature is shown in Fig. 8. All the temperature plots are characteristic of the test circuit with the indicated component types and values given in Fig. 3.

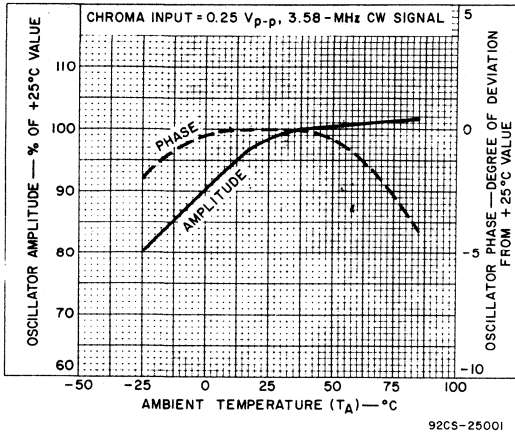


Fig. 6—Amplitude and phase variations of oscillator output vs. temperature.

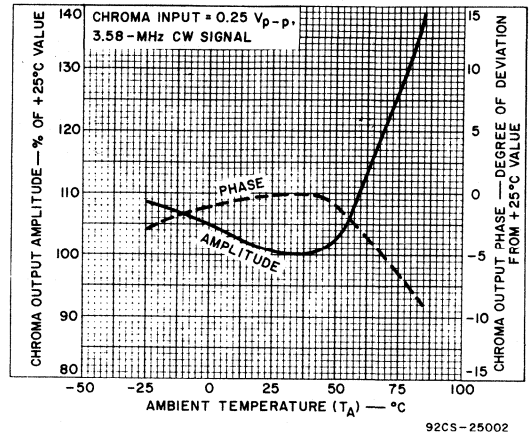


Fig. 7—Amplitude and phase variations of chroma output vs. temperature.

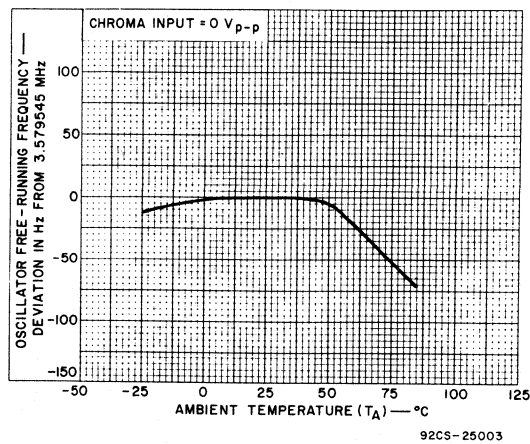
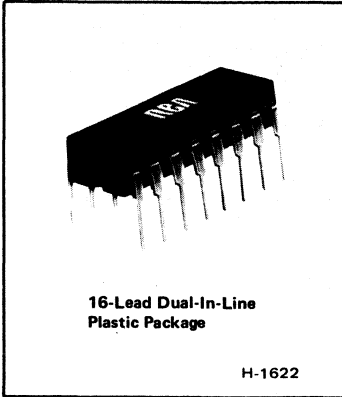


Fig. 8—Variation of oscillator free-running frequency vs. temperature.



TV Chroma Demodulator

Features:

- *Balanced chroma demodulators*
- *Color difference matrix (6500° K)*
- *DC tint control*
- *Three low-output-impedance drivers for direct coupling*
- *Reference subcarrier limiter*
- *Internal RF filtering*
- *DC chroma gain control*
- *Dynamic "flesh correction" – corrects purple and green flesh colors without affecting primary red, green, and blue colors*

The RCA-CA3137E is a monolithic silicon integrated circuit that performs the demodulation, dynamic "flesh correction", tint control, and chroma gain-control functions. It is designed to function compatibly with the CA3126Q Chroma Processor, and is supplied in the 16-lead dual-in-line plastic package.

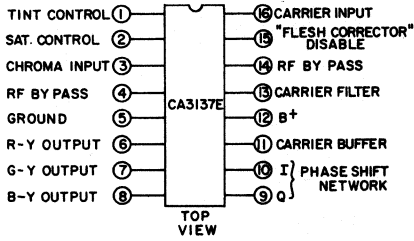
- *Requires few external components*
- *No tuning adjustments are necessary*

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$:

DC SUPPLY VOLTAGE (Between Terms. 5 and 12)	13.2 V
DEVICE DISSIPATION:	
Up to $T_A = 55^\circ\text{C}$	750 mW
Above $T_A = 55^\circ\text{C}$	derate linearly 7.9 mW/ $^\circ\text{C}$
AMBIENT-TEMPERATURE RANGE:	
Operating	-40 to +85 $^\circ\text{C}$
Storage	-65 to +150 $^\circ\text{C}$
LEAD TEMPERATURE (During soldering):	
At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10s max.	+265 $^\circ\text{C}$

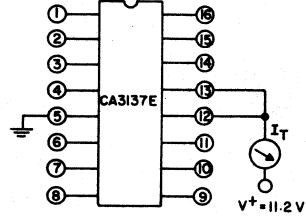
Linear Integrated Circuits

CA3137E



92CS-26907

Fig.1 - CA3137E terminal assignment.



92CS-26906

Fig.2 - DC test circuit.

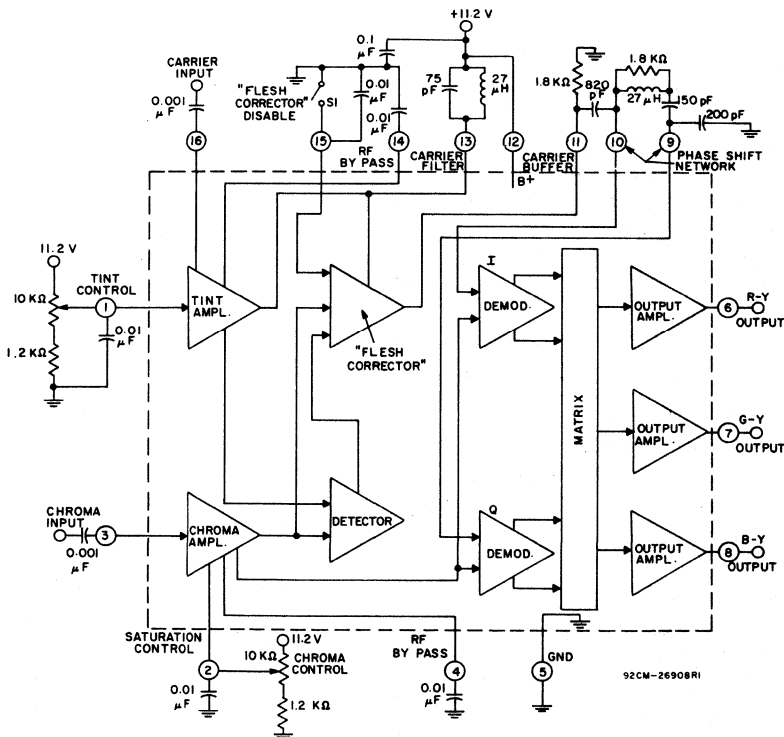


Fig.3 - Functional diagram and typical dynamic test circuit.

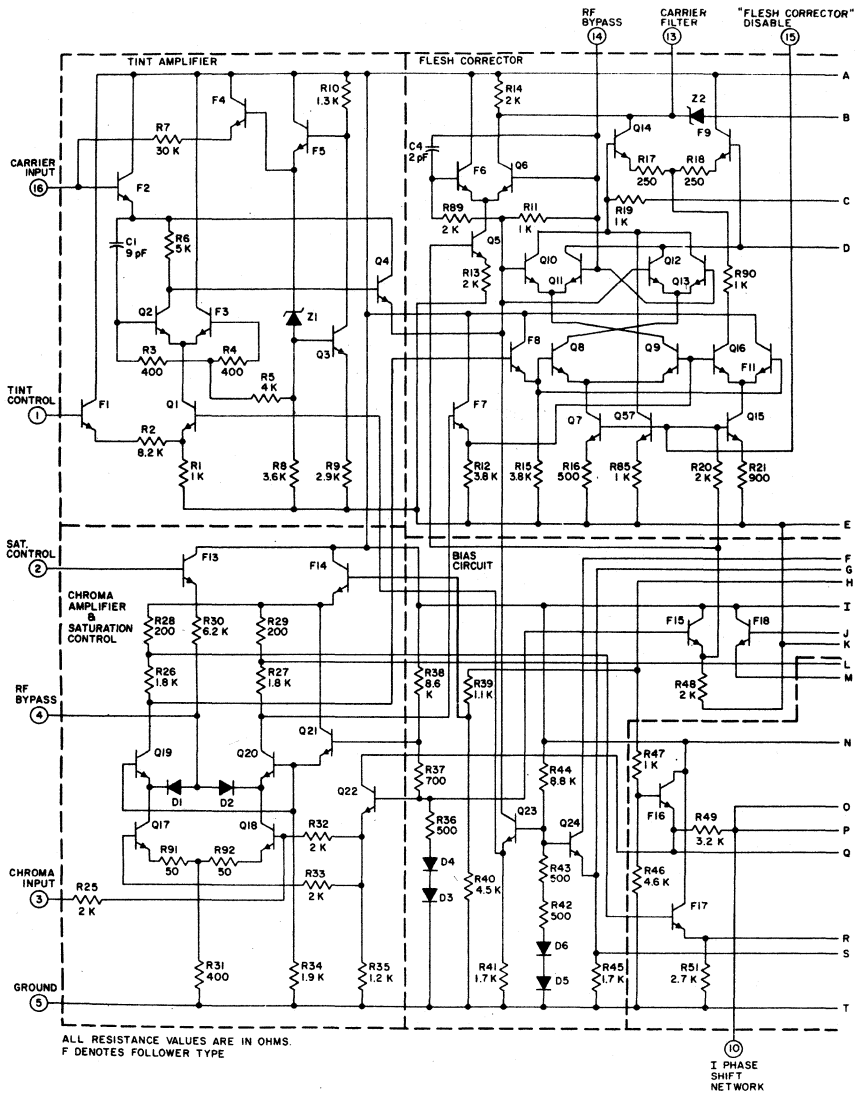


Fig.4 - CA3137E Schematic diagram.

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CA3137E

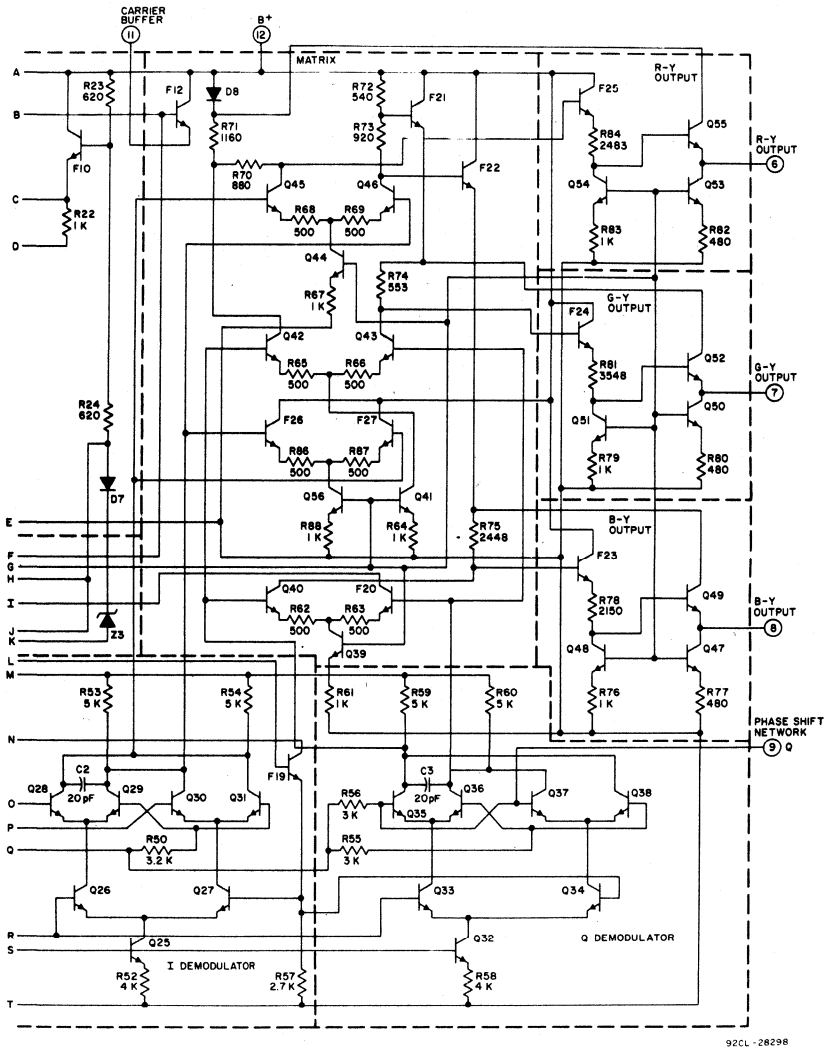


Fig.4 - CA3137E Schematic diagram.

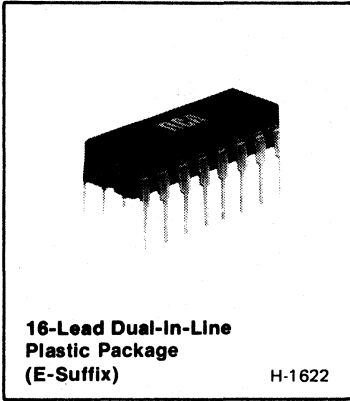
ELECTRICAL CHARACTERISTICS AT $T_A = 25^\circ\text{C}$, $V^+ = 11.2\text{ V}$

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	LIMITS			UNITS
			Min.	Typ.	Max.	
STATIC (See Fig.2)						
Supply Current	I_T		—	35	47	mA
Reference Subcarrier Input	V_{16}		—	6.7	—	VDC
Oscillator Reference Inputs	V_9, V_{10}		—	3.8	—	VDC
R-Y, G-Y, B-Y Outputs	V_6, V_7, V_8		—	5	—	VDC
Chroma Input	V_3		—	1.2	—	VDC
DYNAMIC (See Fig.3)						
Tint and Sensitivity Limiting	V_{11}	$V_{16} = 200\text{ mV p-p @ } 3.58\text{ MHz}$	200	300	—	mVp-p
Tint Limiting	V_{11}	$V_{16} = 800\text{ mV p-p @ } 3.58\text{ MHz}$	—	425	600	mVp-p
Tint Amplifier* Phase Reference	ϕV_{11}	$V_{16} = 400\text{ mV p-p}$, Term.1 = 11.2 VDC	-35	-25	-15	Degrees
Tint Control [▲] Range	$\Delta\phi_{11}$	$V_{16} = 800\text{ mV p-p}$, Term.1 = 1.2 VDC	-130	-110	-80	Degrees
Ratio G-Y to R-Y	V_7/V_6	$V_{16} = 400\text{ mV p-p}$, $V_3 = 40\text{ mV p-p}$	28	33	38	%
Ratio B-Y to R-Y	V_8/V_6		108	120	132	%
Demodulated Chroma Output R-Y	V_6	$V_{16} = 400\text{ mV p-p}$, $V_3 = 40\text{ mV p-p}$	350	550	—	mV p-p
Color Difference Output (Bandwidth at 3 dB)		$V_3 = 40\text{ mV p-p}$	—	900	—	kHz
Maximum Color Difference Outputs:						V_{p-p}
	R-Y V_6	$V_{16} = 400\text{ mV p-p}$, $V_3 = 300\text{ mV p-p}$	1.5	2.2	—	
	G-Y V_7		0.42	0.7	—	
	B-Y V_8		1.6	2.65	—	
"Flesh Detector" Reference:		Set-Up: Term.2 = 1.6 V Term.1 = 11.2 V Term.16 = 400 mV p-p @ 0° Reference Angle Term.3 = 40 mV p-p @ 10° Reference Angle S ₁ Closed (Term.15 at GND)	Reference Set-Up			
"Flesh Detector": Phase	ϕ_{11}	Same Set-up except S ₁ open	—	0	—	Degrees
Amplitude	V_{11}		—	275	—	%
"Flesh Detector": Phase	ϕ_{11}	Same Set-up except Term.3 at 190° angle	—	0	—	Degrees
Amplitude	V_{11}		—	100	—	%
Small-Signal Output Resistance (Terms.6,7,8)	r_o		—	50	—	Ω
Small-Signal Input Resistance:						
	Term.3	r_i	—	3	—	k Ω
	Terms.9&10		—	2.5	—	

* Phase angle of term. 11 referenced to term. 16 phase angle.

▲ Phase angle of term. 11 with term. 1 = 1.2 V minus phase angle of term. 11 with term. 1 = 11.2 V.

CA3145E



TV Chroma Amplifier/ Demodulator

Provides Complete System for Processing Chroma When Used with RCA-CA3158E

FEATURES:

- Excellent linearity in dc chroma gain-control circuit
- Improved filtering resulting in reduced 7.2 MHz output from the color demodulators
- Current limiting for short-circuit protection
- Good tolerance to B + supply variations

The RCA-CA3145E is a monolithic silicon integrated circuit chroma amplifier/demodulator with ACC and killer control for color-TV receivers. It is designed to function compatibly with the CA3158E in a two-package chroma system. Figs. 4 and 5 show a functional block diagram and the outboard circuitry of a typical two-package chroma system incorporating the CA3145E and CA3158, respectively.

- Excellent temperature coefficient stability
- Operation from + 12 V supply

The CA3145E is supplied in a 16-lead dual-in-line plastic package.

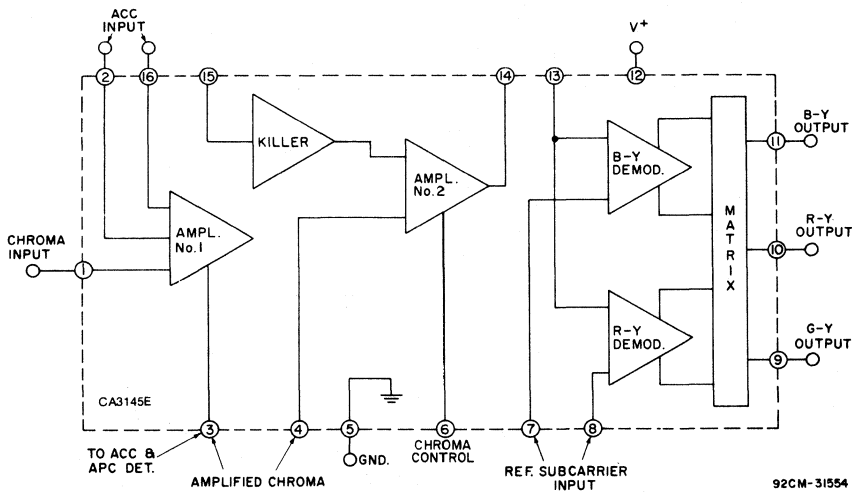


Fig. 1 — Functional block diagram of the CA3145E.

Linear Integrated Circuits

CA3145E

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V_2 = V_{16} = 8\text{ V}$,
 $V_1 = V_3 = V_4 = V_{13} = \text{GND}$ Unless otherwise specified (See Fig. 2)

CHARACTERISTICS	SWITCH NUMBERS			SPECIAL TEST CONDITIONS	LIMITS		UNITS
	S1	S2	S3		Typ.	Max.	
	SWITCH POSITIONS						
Static							
Supply Current, I^+	1	1	1		35	—	mA
First Chroma Bias Voltage	1	1	1	Meas. Term. 1	3	—	V
First Chroma D.C. Output Voltage	1	1	1	Meas. Term. 3	9	—	V
Second Chroma Bias Voltage	2	1	1	Meas. Term. 4	3.1	—	V
B-Y Reference Voltage	2	1	1	Meas. Term. 7	4.2	—	V
R-Y Reference Voltage	2	1	1	Meas. Term. 8	4.2	—	V
B-Y DC Output Voltage	2	1	2	Meas. Term. 11	7.5	—	V
R-Y DC Output Voltage	2	1	2	Meas. Term. 10	7.5	—	V
G-Y DC Output Voltage	2	1	2	Meas. Term. 9	7.5	—	V
Vdc Difference Between Any Two Outputs	—	—	—	V10 – V11	—	±350	mV
				V9 – V11	—	±350	
				V11 – V13	—	±350	
Dynamic							
First Chroma Gain, V3	1	1	1	V1=106 mV RMS, f=3.56 MHz, Meas. V3	0.4	—	V _{RMS}
Second Chroma Gain, V14	1	1	1	V4=150 mVRMS, f=3.56 MHz, Meas. V14	0.6	—	V _{RMS}
Second Chroma 2/3 Gain, V14	1	2	1	V4=150 mVRMS, f=3.56 MHz, Meas. V14	0.65	—	
Second Chroma 1/3 Gain, V14	1	3	1	V4=150 mVRMS, f=3.56 MHz, Meas. V14	0.3	—	
Demodulator Conversion Gain (B-Y), V11	1	1	1	V13=35 mVRMS, f=3.56 MHz	0.45	—	V _{RMS}
Relative Gain, R-Y to B-Y; V10	1	1	1	V13=35 mVRMS, f=3.56 MHz	0.8	—	V _{RMS}
Relative Gain, G-Y to B-Y; V9	1	1	1	V13=35 mVRMS, f=3.56 MHz	0.25	—	V _{RMS}
Phase Difference, R-Y to B-Y; Term. 10 to Term. 11	1	1	1	V13=35 mVRMS, f=3.56 MHz	–105	—	Degrees
Phase Difference, G-Y to B-Y; Term. 9 to Term. 11	1	1	1	V13 = 35 mVRMS, f=3.56 MHz	108	—	Degrees
Killer Action, V14	1	1	1	V15 = 1 V _{p-p} 200 KHz square wave	1.2	—	V _{p-p}

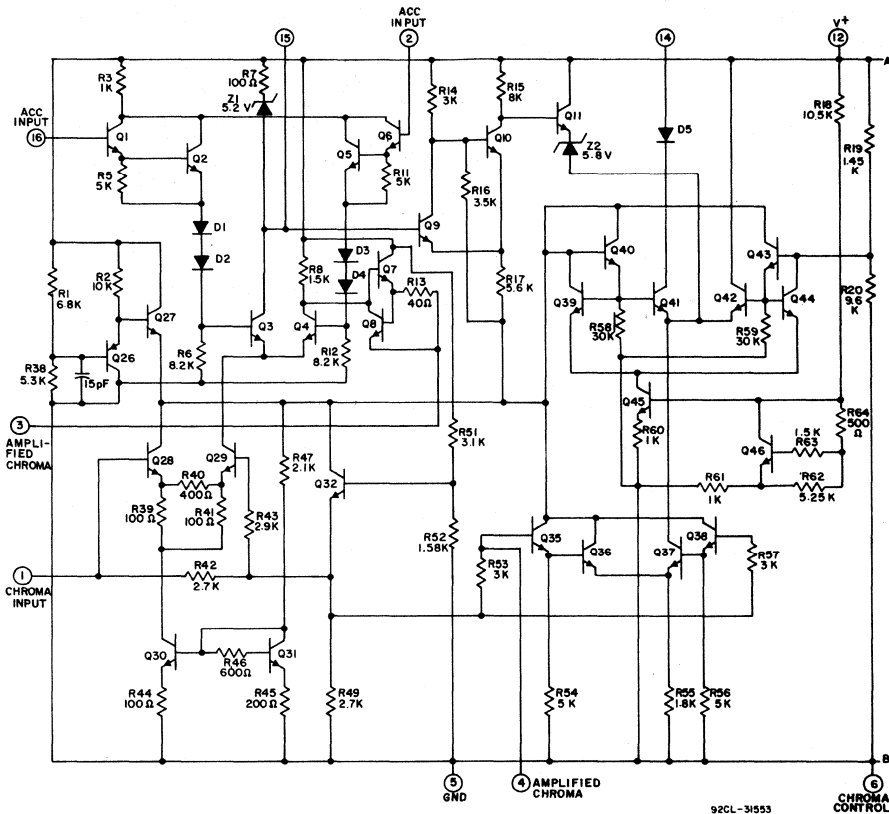


Fig. 3 - Schematic diagram of the CA3145E (cont'd on next page).

Circuit Description

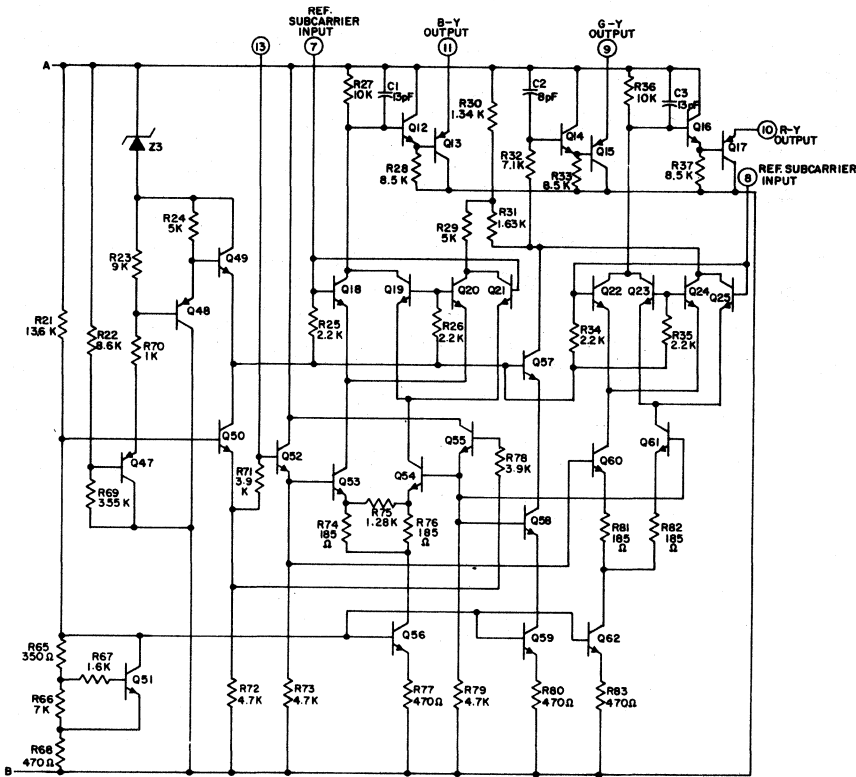
The chrominance input signal applied to terminal 1 is amplified by the differential amplifier Q28 - Q29. The output current of amplifier Q28 - Q29 is applied to a second differential amplifier, Q3 - Q4. The current division in Q3 - Q4, and therefore the gain of each transistor, is determined by the automatic-chroma-control (ACC) differential voltage applied to terminals 2 and 16 from a subcarrier regenerator, such as the CA3158G. As more current is shifted to Q4, the gain of this transistor is increased so that a larger signal is developed across resistor R8. At a preset condition of decreased current in Q3, the color killer (Q3 - Q4) is activated. Terminal 15 is externally connected to an adjustable voltage-divider resistor network which is preset to the desired killer threshold. When the current through Q3 is high, the terminal 15 voltage is low enough to be clamped by Z1, which prevents saturation of Q3. As the current is shifted from Q3 to Q4, the terminal 15 voltage rises, and eventually the Schmitt trigger (Q9 - Q10) is triggered. This triggering action reduces the

second-stage current. The chroma signal at R8 is delivered to terminal 3 by the short-circuit-protected emitter follower Q7.

Current for the first amplifier stage is derived from the internal 5.3-V supply (Q26 - Q27) and the current mirror (Q30 - Q31). The killer threshold is dependent upon this current, but the signal gain is substantially controlled by the resistor ratio of R8 and the Q28 and Q29 emitter resistor network.

The output from terminal 3 is applied to the second amplifier input (terminal 4). This signal is amplified by the differential amplifier Q36 - Q37 and attenuated by the differential amplifier Q41 - Q42. The output current flows through terminal 14 to an external tuned load. The amount of current in this stage is determined by the value of R55 and the voltage across it. The voltage is provided by an internal bias supply to Q35 and Q38 for the Darlington differential amplifier. The second-amplifier gain is determined by the transconductance (gm) of the Q36 - Q37 differential amplifier. The gain is approx-

CA3145E



92CL - 31553

Fig. 3 - Schematic diagram of the CA3145E (cont'd from previous page).

Circuit Description (cont'd)

imately gmR_L where R_L is the external load at terminal 14 and gm is determined by the current in the differential amplifier. The input is attenuated by a divider formed by an external resistor and R53. The divider circuit compensates for gain variations due to resistance variations in R55 where such variations also affect R53.

The variable attenuation at the differential amplifier Q41 - Q42 is the manual gain-control function. The differential control-voltage on the differential amplifier is not linearly related to the current division (gain). In this system, the control voltage is derived from another differential pair, Q39 - Q44, which develops a compensating characteristic based on the division current in that pair. The source of current for the control is the Q45 - Q46 current mirror, which is

designed to provide a current that has little dependence upon V_{BE} or beta. When terminal 6 is low, the voltage at the R19 - R20 junction is such that the current from Q45 flows through Q41, which is the maximum-gain condition. As the terminal 6 voltage is raised, more and more of the Q45 current passes through Q44 and R19 - R20, while more and more of the signal-carrying current is passed through Q42 to the supply. The diode D5 limits current flow in the event that terminal 14 is shorted to ground.

The negative R-Y and B-Y currents are combined in resistor values chosen to provide the correct signal gain for the G-Y output. The resistive ladder circuit is level-controlled by a current source from Q57 which applies the current required to set the correct level. The current sources are designed with equal-value emitter resistors to facilitate balancing.

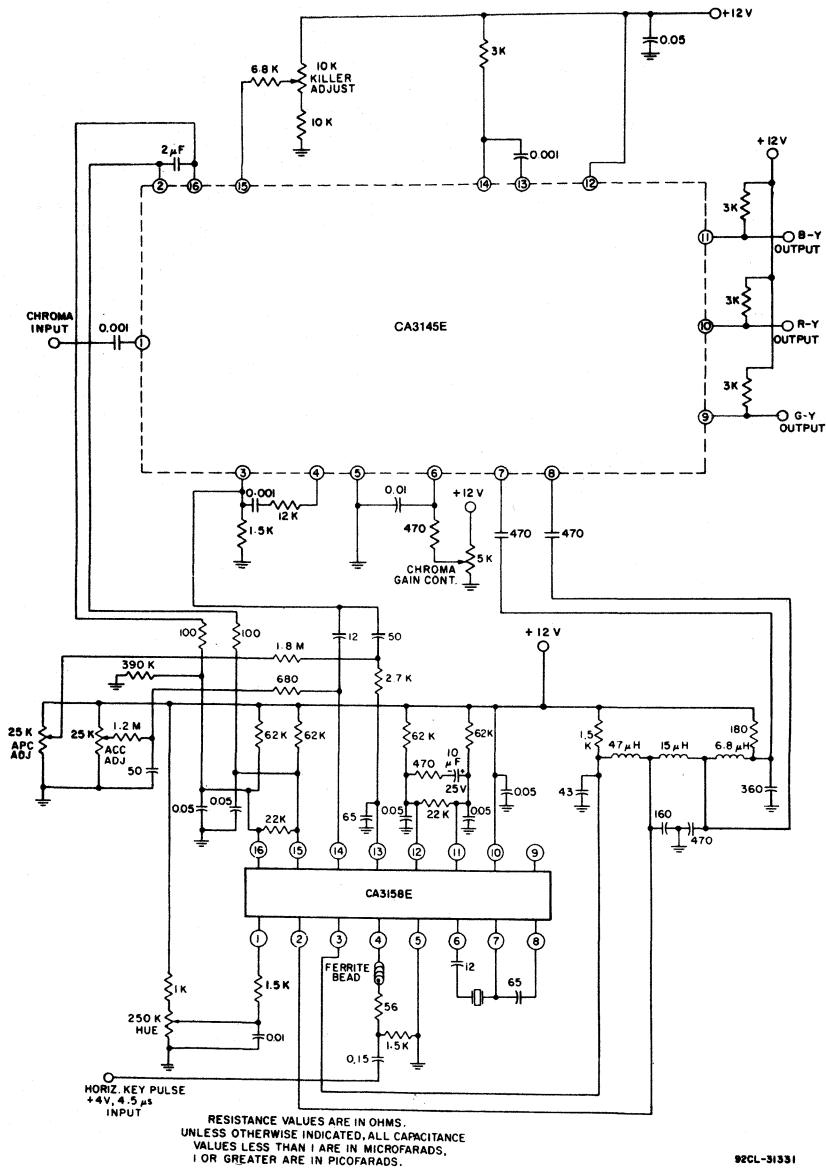


Fig. 4 — Output circuitry of a typical two-package chroma system for color-TV receivers utilizing the CA3145E and CA3158E.

CA3145E

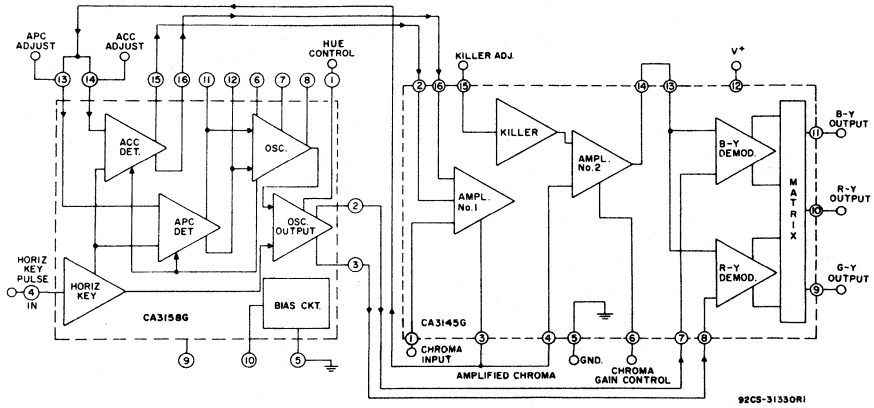


Fig. 5 — Simplified functional diagram of a two-package TV chroma system utilizing the CA3145E and CA3158E.



24-Lead Dual-in-Line
Plastic Package
"E"-Suffix Type

H-1888

Single Chip TV Chroma Processor/Demodulator

FEATURES:

- All chroma processing and demodulating circuitry on a single chip in a 24-lead plastic package
- Phase-locked subcarrier regeneration utilizing sample-and-hold techniques
- Supplementary ACC with overload detector to prevent over saturation of the picture tube

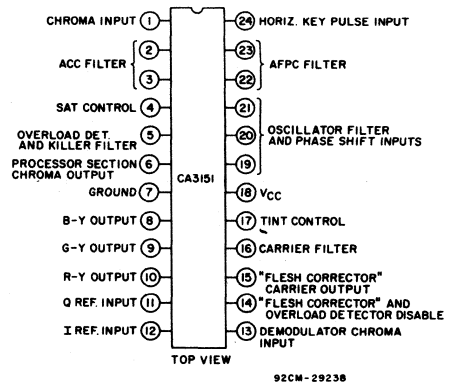
The RCA-CA3151E is a monolithic silicon integrated circuit that performs the complete chroma processor and demodulating functions for color TV. This simple chip contains all the features of the CA3126 chroma processor and the CA3137 chroma demodulator.

The CA3151E is supplied in the 24-lead dual-in-line plastic package.

- Linear dc controls for chroma gain and tint
- Dynamic "flesh correction"—corrects purple and green flesh colors without affecting primary colors
- Balanced chroma demodulators with low output impedance for direct coupling
- Internal rf filtering
- Requires few external components
- Low system dissipation—nominal 0.5 W

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE:	
Between Terminals 18 and 7	13.2 V
DEVICE DISSIPATION:	
Up to $T_A = 55^\circ\text{C}$	825 mW
Above $T_A = 55^\circ\text{C}$	Derate linearly at 8.7 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:	
Operating	-40 to +85 $^\circ\text{C}$
Storage	-65 to +150 $^\circ\text{C}$
LEAD TEMPERATURE (During Soldering):	
At distance 1/16 ± 1/32 inch (1.59 ± 0.79 mm) from case for 10 seconds max.	+265 $^\circ\text{C}$



92CM-29238
TERMINAL DIAGRAM

Linear Integrated Circuits

CA3151E

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V^+ = 11.6\text{ V}$

CHARACTERISTIC	TEST CONDITIONS						TYPICAL VALUE	UNITS	
	S ₁	S ₂	S ₃	Chroma In	Burst In	V ₄			V ₁₇
STATIC (See Fig. 1)									
Supply Current, I _T							42	mA	
R-Y, G-Y, B-Y, Outputs, V ₈ , V ₉ , V ₁₀							5.3	V _{dc}	
Oscillator Reference Inputs, V ₁₁ , V ₁₂							3.7		
Chroma Demodulator Input, V ₁₃							2.9		
Chroma Processor Input, V ₁							2.2		
DYNAMIC (See Fig. 2)									
Minimum Oscillator Pull-In Range*, V ₁₂	2	1	1				±300	Hz	
Oscillator Level, V ₁₂	2	1	1			1.5 V	0.6	V _{p-p}	
100 Percent ACC, V ₁₃	1	1	1				1		
Minimum Gain Control, V ₁₃	1	1	1			11.6 V	20		mV _{p-p}
50 Percent Gain Control, V ₁₃	1	1	1			6 V	50	% of 100% ACC Value	
200 Percent ACC, V ₁₃	1	1	1				100		
20 Percent ACC, V ₁₃	1	1	1				100		
Maximum Kill Output, V ₁₃	1	1	1	54.6 mV _{p-p}	4 mV _{p-p}	7 V	20	mV _{p-p}	
Minimum Unkill Output, V ₁₃	1	1	1		30 mV _{p-p}				400
Overload Detector (OLD), V ₁₃	1	1	2	546 mV _{p-p}		1.5 V	1	V _{p-p}	
R-Y Sensitivity, V ₁₀ E _g = 282 mV _{p-p} , 3.53 MHz	1	2	1						0.8
R-Y Ratio B-Y/R-Y, V ₈ **	1	2	1	0	273 mV _{p-p}			120	%
G-Y Ratio G-Y/R-Y, V ₉ **	1	2	1					33	
Max. R-Y Output, V ₁₀ E _g = 2 V _{p-p} , 3.53 MHz	1	2	1					3	
Minimum Tint Control Range, φ ₁₃	1	1	1			0 V to 11.6 V	80	Degrees	

* Tune C₂ to 3,579,845 Hz with S₁ in position 2. Put S₁ in position 1, and check for pull in. Repeat for frequency tuned to 3,579,245 Hz. For other tests, frequency tuned to 3,579,545 ± 10 Hz. ** All input levels up to 2 V_{p-p}

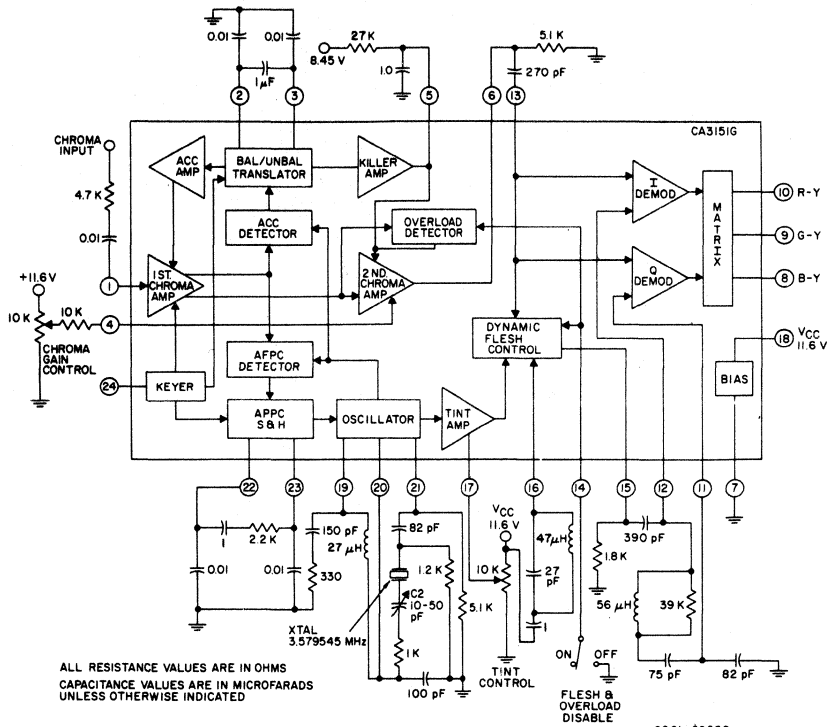


Fig. 1 - Functional diagram, static test circuit, and typical application circuit.

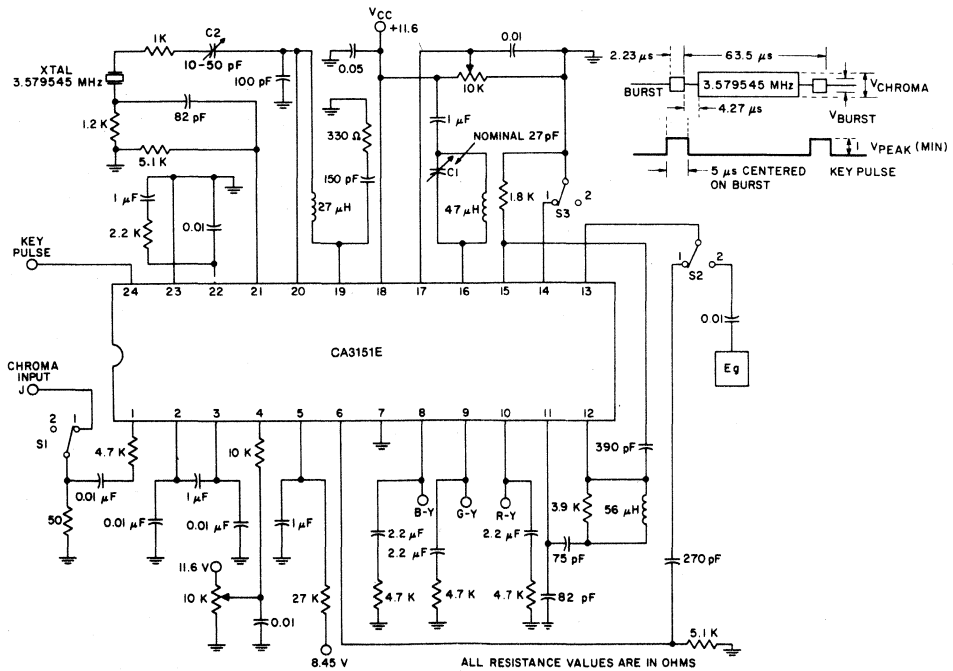


Fig. 2 - Dynamic test circuit.

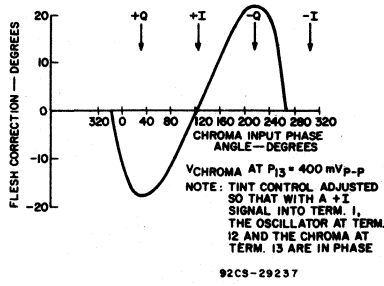
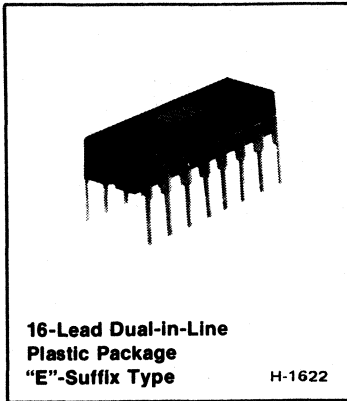


Fig. 3 - "Flesh" correction of oscillator phase angle as a function of chroma input phase angle.



TV Chroma System

FEATURES:

- Voltage-controlled oscillator
- Keyed APC and ACC detectors
- DC hue control
- Operates from +12 V

The RCA-CA3158E* is a monolithic silicon integrated circuit that performs the functions of subcarrier regeneration, ACC and APC detection, and tint control in color television receivers. It is designed to function compatibly with the CA3145E TV Chroma Amplifier/Demodulator in a 2-package chroma system.

The CA3158E is a TV Chroma System equivalent to the CA3170E except that the typical supply voltage is +12 volts and no internal shunt regulator is incorporated.

The CA3158E is supplied in the 16-lead dual-in-line plastic package.

*Formerly Developmental Type No. TA6895G.

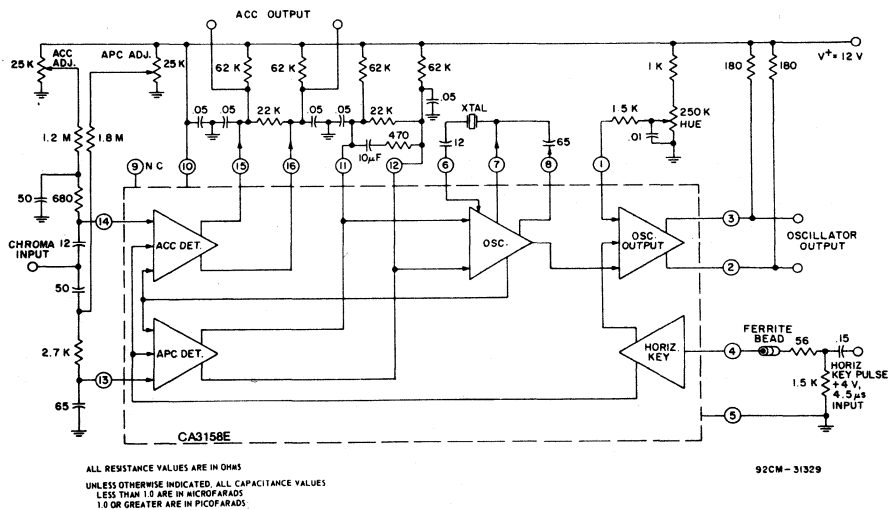


Fig. 1 — Functional block diagram of CA3158E.

Linear Integrated Circuits

CA3158E

MAXIMUM RATINGS, *Absolute-Maximum:*

DC SUPPLY VOLTAGE	15 V
DEVICE DISSIPATION:	
Up to $T_A = 55^\circ\text{C}$	630 mW
Above $T_A = 55^\circ\text{C}$	derate linearly 6.6 mW/ $^\circ\text{C}$
AMBIENT-TEMPERATURE RANGE:	
Operating	-40 to $+85^\circ\text{C}$
Storage	-65 to $+150^\circ\text{C}$
LEAD TEMPERATURE (During soldering):	
At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10 s max.	$+265^\circ\text{C}$

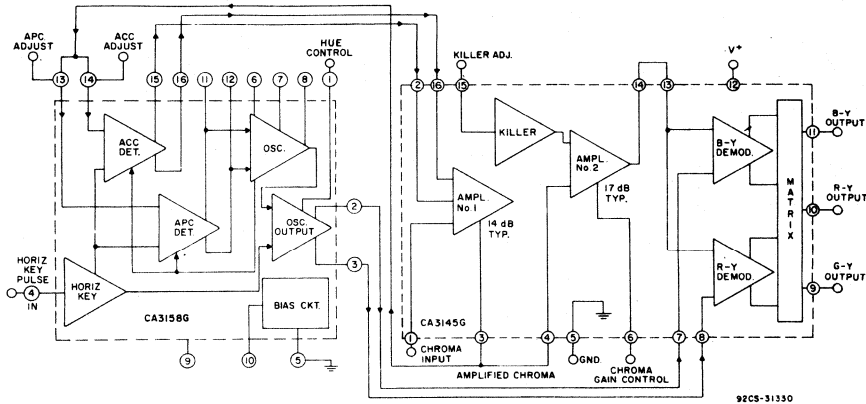


Fig. 2 — Simplified functional diagram of a two-package TV chroma system utilizing the CA3158E and CA3145E.

CIRCUIT DESCRIPTION

The CA3158E is a complete subcarrier regeneration system with automatic phase control applied to the oscillator. An amplified chroma signal from the CA3145E is applied to terminals No. 13 and No. 14, which are the automatic phase control (APC) and the automatic chroma control (ACC) inputs. APC and ACC detection is keyed by the horizontal pulse which also inhibits the oscillator output amplifier during the burst interval. The ACC system uses a synchronous detector to develop a correction voltage at the differential output terminal Nos. 15 and 16. This control signal is applied to the input terminal Nos. 2 and 16 of the CA3145E. The APC system also uses a synchronous detector. The APC error voltage is internally coupled to the 3.58 MHz oscillator at balance; the phase of the signal at terminal No. 13 is in quadrature with the oscillator. To accomplish phasing requirements, an RC phase shift network is used between the chroma input and terminal Nos. 13 and 14. The feedback loop of the oscillator is from

terminal Nos. 7 and 8 back to No. 6. The same oscillator signal is available at terminal Nos. 7 and 8, but the dc output of the APC detector controls the relative signal levels at terminal Nos. 7 or 8. Because the output at terminal No. 8 is shifted in phase compared to the output at terminal No. 7, which is applied directly to the crystal circuit, control of the relative amplitudes at terminal Nos. 7 and 8 alters the phase in the feedback loop, thereby changing the frequency of the crystal oscillator. Balance adjustments of dc offsets are provided to establish an initial no-signal offset control in the ACC output, and a no-signal, on-frequency adjustment through the APC detector-amplifier circuit which controls the oscillator frequency. The oscillator output stage is differentially controlled at terminal Nos. 2 and 3 by the hue control input to terminal No. 1. The hue phase shift is accomplished by the external R, L, and C components that couple the oscillator output to the demodulator input terminals. The CA3158E operates from a 12-volt dc supply.

Linear Integrated Circuits

CA3158E

ELECTRICAL CHARACTERISTICS At $T_A = 25^\circ\text{C}$, $V^+ = 12\text{ V}$ unless otherwise specified

CHARACTERISTIC	SWITCH NUMBERS			SPECIAL TEST CONDITIONS	LIMITS		UNITS
	S1	S2	S3		Min.	Max.	
	SWITCH POSITIONS						
STATIC (See Fig. 6)							
Supply Current, I^+	1	1	1		12	24	mA
Oscillator Current, I_2	1	2	1		4.25	8.55	
ACC Output Balance	2	2	1	Measure Term. 15 to 16	-330	300	mV
APC Output Balance	2	2	1	Measure Term. 11 to 12	-450	450	
Oscillator Balance	2	3	2	Measure Term. 7 to 8	-330	330	
DYNAMIC (See Fig. 8); $e_{IN} = 0.4\text{ V p-p sine wave}$							
Oscillator Center Frequency, f_O	1	2	1	Set R for $f_O = 3579545 \pm 5\text{ Hz}$	-	-	Hz
Oscillator Frequency Deviation, f_{O1}	1	1	1		-400	400	
Oscillator Frequency Deviation, $ \Delta f_O $	1	2	1	$V^+ = 12\text{ V} \pm 1\text{ V}$	-	175	
Oscillator Pull-In Range: High Frequency Side Low Frequency Side	1	2	2	Osc. must pull-in and lock to e_{IN} at: $f_{IN} = 3.579745\text{ MHz}$ $f_{IN} = 3.579345\text{ MHz}$	200 -200	- -	
Dynamic ACC	2	2	1	Measure Term. 15 to 16 Record value (V1)	-75	75	mV
ACC Control	2	2	2	Measure Term. 15 to 16, $f_{IN} = 3.579545\text{ MHz}$	Record Value (V2)		
$\Delta\text{ ACC Control}$	-	-	-	Limits for $\Delta\text{ ACC Control} = V2 - V1$	120	250	
Dynamic APC	1	2	1	Tap of R to ground	1	12	V

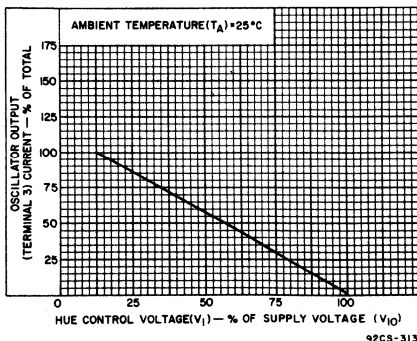


Fig. 4 — Typical hue control characteristic.

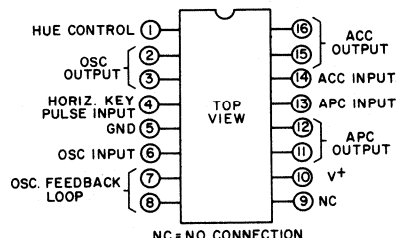


Fig. 5 — Terminal diagram of the CA3158E.

Linear Integrated Circuits

CA3158E

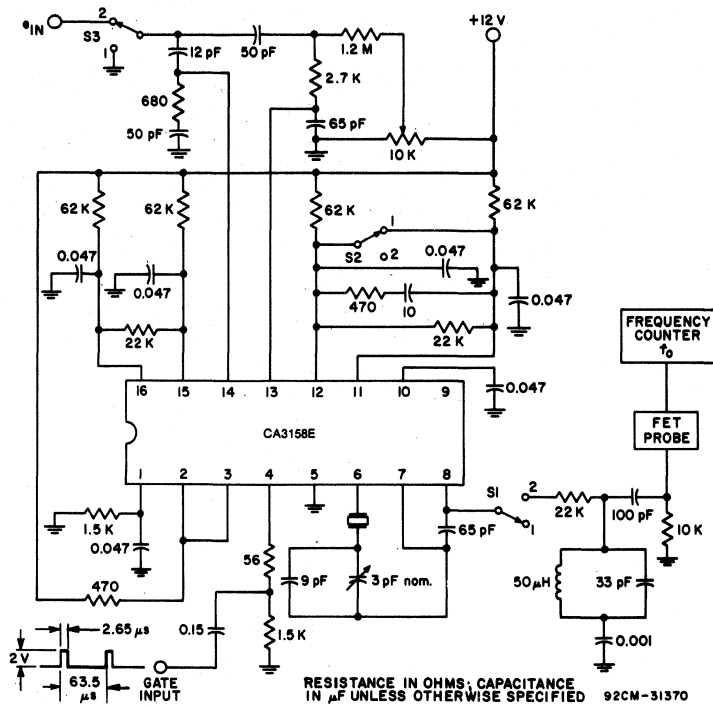
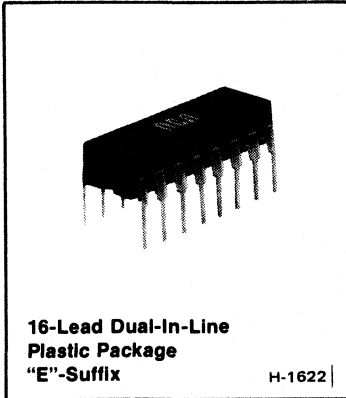


Fig. 8 - Dynamic characteristics test circuit.

TV Chroma System



FEATURES:

- Voltage-controlled oscillator
- Keyed APC and ACC detectors
- DC hue control
- Shunt regulator

The RCA-CA3170E is a monolithic silicon integrated circuit that performs the functions of subcarrier regeneration, ACC and APC detection, and tint control in color television receivers. It is designed to function compatibly with the CA3121E TV Chroma Amplifier/Demodulator in a 2-package chroma system.

The CA3170E is a TV Chroma System of advanced design

that incorporates all the features of the CA3070E but with the added advantage of the modified Hue Control Characteristic. With the CA3170E, the designer can provide a front panel hue control that functions linearly over its entire range, a particularly desirable consumer feature.

The CA3170E is supplied in the 16-lead dual-in-line plastic package.

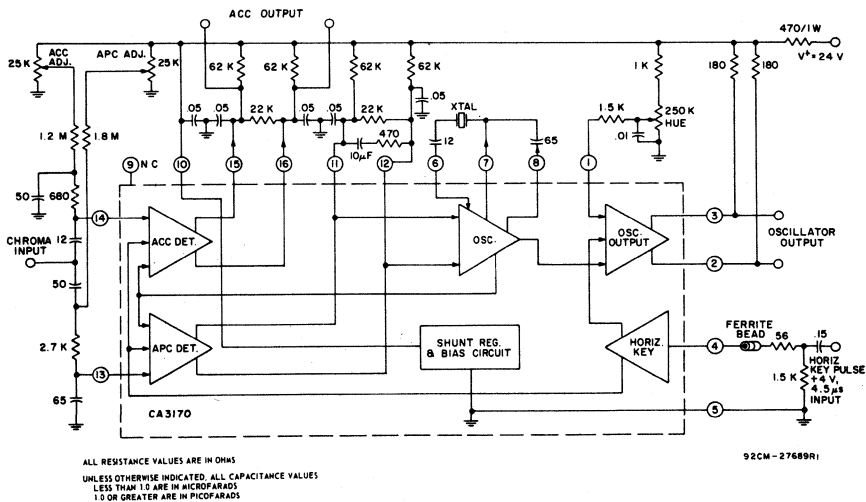


Fig. 1 — Functional block diagram of CA3170E.

Linear Integrated Circuits

CA3170E

ELECTRICAL CHARACTERISTICS, at $T_A = 25^\circ\text{C}$ and $V^+ = +24\text{ V}$ unless otherwise specified

CHARACTERISTICS	SPECIAL TEST CONDITIONS	LIMITS			UNITS	
		CA3170G				
		MIN.	TYP.	MAX.		
Static Characteristics						
Voltage: Hue Control, V_1	See Fig. 7				V	
Oscillator Input, V_6	S ₁ CLOSED S ₃ OFF; S ₂ , S ₄ , S ₅ OPEN See Fig. 8	-	2.6	-		
APC Input, V_{13}		-	5.4	-		
Regulator, V_{10}		$V^+ = 21\text{ V}$	11	12.3		13.5
Regulator Change, V_{10}		$V^+ = 27\text{ V}$	-0.2	-		+0.2
Horizontal Key Input, V_4	$I_4 = -10\ \mu\text{A}$	5	-	-		
Currents: Oscillator Output, I_2	S ₁ , S ₂ , S ₄ , S ₅ CLOSED, S ₃ in position 2, See Fig. 8	-	5.8	-	mA	
APC Output, I_{11} , I_{12}	S ₁ , S ₅ OPEN, S ₂ , S ₄ CLOSED, S ₃ in position 1, See Fig. 8	-	1.45	-		
ACC Output, I_{15} , I_{16}	S ₃ in position 1, See Fig. 8	-	1.45	-		
Dynamic Characteristics (See Figure 6)						
Oscillator Outputs: Terminal No. 2, V_2	S ₁ in position 1	0.75	1.0	-	V_{p-p}	
Terminal No. 3, V_3	S ₁ in position 2	0.75	1.0	-		
ACC Detected Output $V_{16} - V_{15}$	S ₁ in position 1	115	150	-	mV	
Oscillator Pull-In Range	S ₁ in position 1	-	± 400	-	Hz	

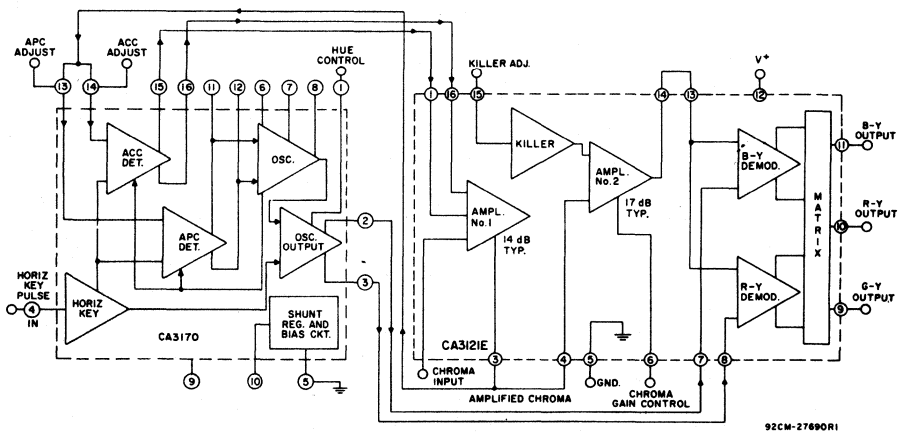


Fig. 2 Simplified functional diagram of a two-package TV chroma system utilizing the CA3170E and CA3121E.

CIRCUIT DESCRIPTION

The CA3170E is a complete subcarrier re-generation system with automatic phase control applied to the oscillator. An amplified chroma signal from the CA3121E is applied to terminals No. 13 and No. 14, which are the automatic phase control (APC) and the automatic chroma control (ACC) inputs. APC and ACC detection is keyed by the horizontal pulse which also inhibits the oscillator output amplifier during the burst interval. The ACC system uses a synchronous detector to develop a correction voltage at the differential output terminal Nos. 15 & 16. This control signal is applied to the input terminal Nos. 1 & 16 of the CA3121E. The APC system also uses a synchronous detector. The APC error voltage is internally coupled to the 3.58 MHz oscillator at balance; the phase of the signal at terminal No. 13 is in quadrature with the oscillator. To accomplish phasing requirements, an RC phase shift network is used between the chroma input and terminal Nos. 13 and 14. The feedback loop of the oscillator is from

terminal Nos. 7 and 8 back to No. 6. The same oscillator signal is available at terminal Nos. 7 and 8, but the dc output of the APC detector controls the relative signal levels at terminal Nos. 7 or 8. Because the output at terminal No. 8 is shifted in phase compared to the output at terminal No. 7, which is applied directly to the crystal circuit, control of the relative amplitudes at terminal Nos. 7 and 8 alters the phase in the feedback loop, thereby changing the frequency of the crystal oscillator. Balance adjustments of dc offsets are provided to establish an initial no-signal offset control in the ACC output, and a no-signal, on-frequency adjustment through the APC detector-amplifier circuit which controls the oscillator frequency. The oscillator output stage is differentially controlled at terminal Nos. 2 and 3 by the hue control input to terminal No. 1. The hue phase shift is accomplished by the external R, L, and C components that couple the oscillator output to the demodulator input terminals. The CA3170E includes a shunt regulator to establish a 12-volt dc supply.

MAXIMUM RATINGS, Absolute-Maximum:

DEVICE DISSIPATION:*

Up to $T_A = 55^\circ\text{C}$ 750 mW
Above $T_A = 55^\circ\text{C}$ derate linearly 7.9 mW/ $^\circ\text{C}$

AMBIENT-TEMPERATURE RANGE:

Operating -40 to $+85^\circ\text{C}$
Storage -65 to $+150^\circ\text{C}$

LEAD TEMPERATURE (During soldering):

At distance 1/16 \pm 1/32 inch (1.59 \pm 0.79 mm)
from case for 10 s max. $+265^\circ\text{C}$

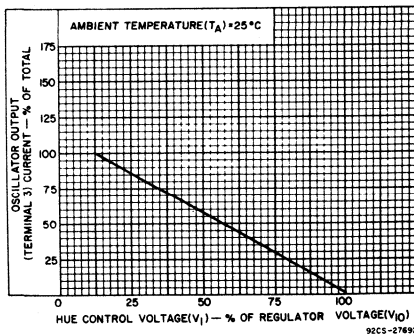


Fig. 3 - Typical hue control characteristic.

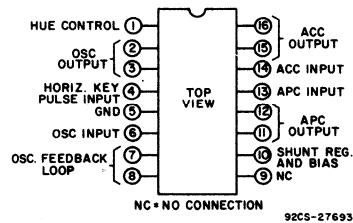


Fig. 4 - Terminal diagram of the CA3170E.

Linear Integrated Circuits

CA3170E

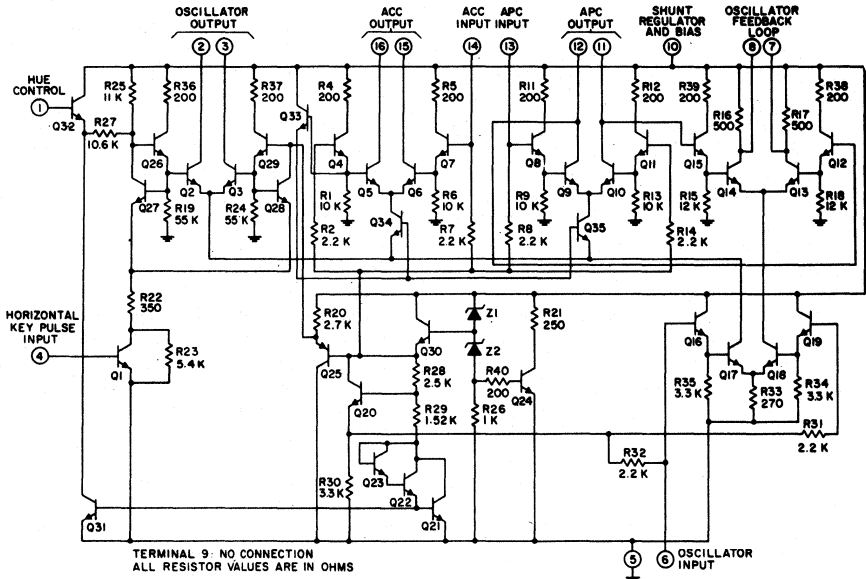


Fig. 5 — Schematic diagram of the CA3170E.

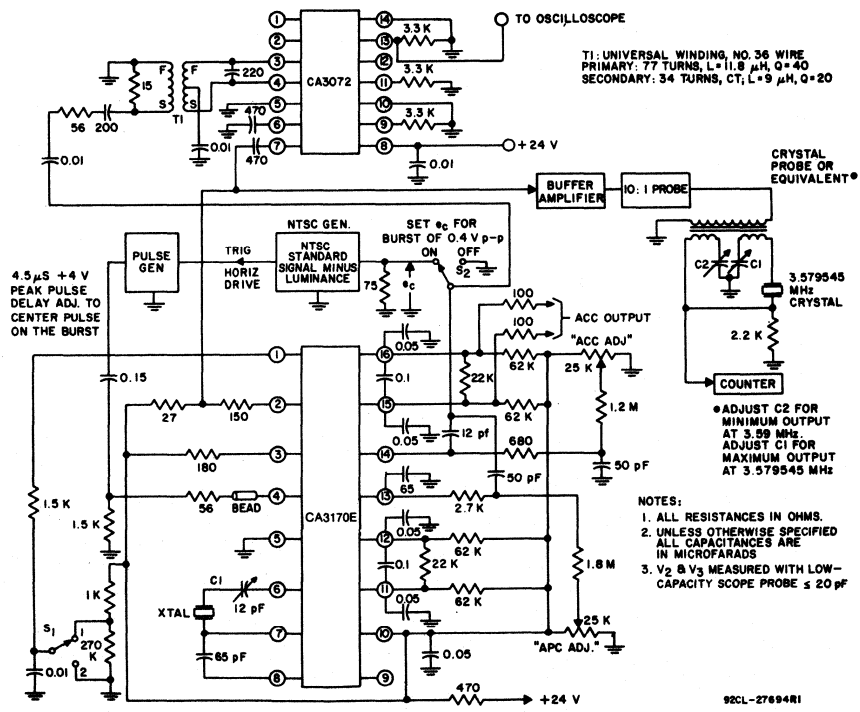


Fig. 6 — Dynamic characteristics test circuit.

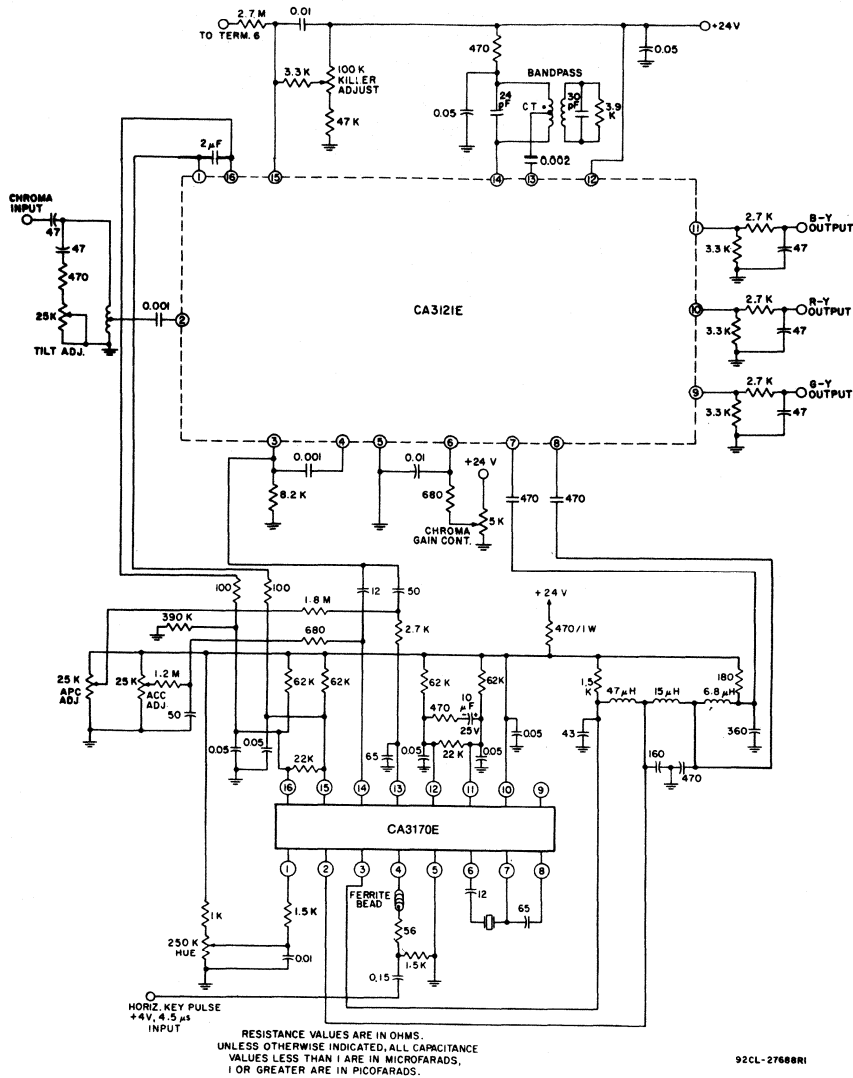


Fig. 7—Outboard circuitry of a typical two-package chroma system for color-TV receivers utilizing the CA3121E and CA3170E.

DYNAMIC TEST PROCEDURE

1. With S2 in "OFF" position, short terminals 11 and 12. Then with S1 in 1 position, adjust CX for a frequency of $3.579545 \text{ MHz} \pm 5 \text{ Hz}$. Measure the frequency using the frequency counter or by zero beat indication on the oscilloscope.
2. Remove short from terminals 11 and 12, and adjust "APC" control for zero beat on the oscilloscope. With S2 in "ON" position, pattern on oscilloscope must lock.
3. With S2 in "OFF" position adjust "ACC" control to give output reading of $0 \pm 2 \text{ mV}$ between terminals 15 and 16. Then with S2 in "ON" position, read "ACC" output.
4. Example of pull-in testing to $\pm 200 \text{ Hz}$:
With S2 in "OFF" position, adjust CX for frequency of $3.579545 + 200 \text{ Hz}$. Then with S1 in position 1 and S2 in "ON" position, pattern on oscilloscope must lock.
5. Repeat Step 4 with CX adjusted to -200 Hz .

Linear Integrated Circuits

CA3170E

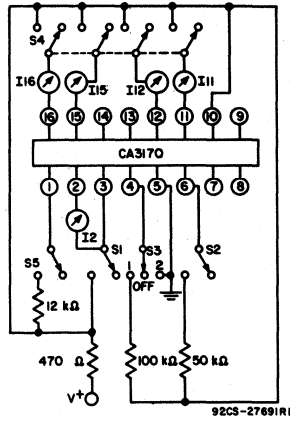
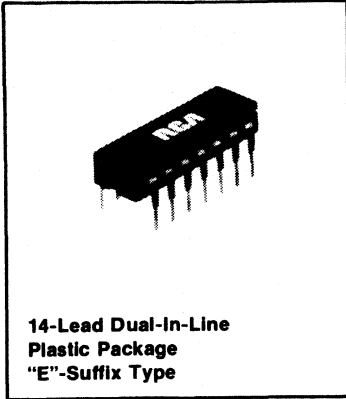


Fig. 8 – Static characteristics test circuit



14-Lead Dual-In-Line
Plastic Package
"E"-Suffix Type

TV Chroma Demodulator

SYSTEM FEATURES:

- Synchronous detector with color-difference matrix
- Emitter-follower output amplifier with short-circuit protection
- Typical R-Y output ratio of 0.95 and 89°, G-Y output ratio of 0.33 and 244°, and B-Y output ratio of 1.0 and 0°

The RCA-CA3172E is a monolithic silicon integrated circuit intended for use as a chroma demodulator in TV applications. It is operated from a 24-volt supply.

The device has synchronous detectors with matrix circuits to achieve the R-Y, G-Y, and B-Y color-difference output signals. The chroma input signal is applied to terminal Nos. 3 and 4, while the oscillator injection signal is applied to terminal Nos. 6 and 7. The color-difference signals, after

matrix, have a fixed relationship of amplitude and phase.

The outputs of the CA3172E are suitable for driving high-level color-difference or R, G, and B output amplifiers. The emitter-follower stages used to drive the high-level color amplifiers have short-circuit protection.

The CA3172E is supplied in a 14-lead dual-in-line plastic package.

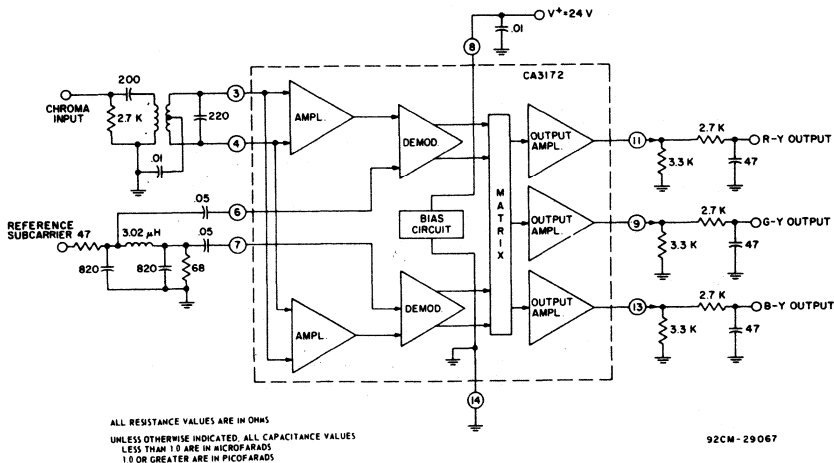


Fig. 1 — Functional diagram of RCA-CA3172E.

Linear Integrated Circuits

CA3172E

MAXIMUM RATINGS, Absolute Maximum-Values at $T_A = 25^\circ\text{C}$

DC SUPPLY VOLTAGE (Terminal 8 to Terminal 14)	27	V
REFERENCE INPUT VOLTAGE	5	V _{p-p}
CHROMA INPUT VOLTAGE	5	V _{p-p}
DEVICE DISSIPATION:		
Up to $T_A = +70^\circ\text{C}$	530	mW
Above $T_A = +70^\circ\text{C}$	Derate Linearly at 6.7 mW/ $^\circ\text{C}$	
AMBIENT TEMPERATURE RANGE:		
Operating	-40 to +85 $^\circ\text{C}$	
Storage	-65 to +150 $^\circ\text{C}$	
LEAD TEMPERATURE (During Soldering):		
At distance 1/32 in. (3.17 mm) from seating plane for 10 s max.	+265 $^\circ\text{C}$	

**Maximum Voltage and Current Ratings
at $T_A = +25^\circ\text{C}$**

Voltage*			Current		
Terminal No.	MIN VOLTS	MAX VOLTS	Terminal No.	I _I mA	I _O mA
3	0	+5	3	-	-
4	0	+5	4	-	-
6	0	+12	6	-	-
7	0	+12	7	-	-
8	0	+27	8	-	-
9	0	+20	9	1.0	20
11	0	+20	11	1.0	20
13	0	+20	13	1.0	20

* With reference to terminal No. 14 and with the voltage between terminal No. 8 and terminal No. 14 at +24 V except as given in rating for terminal No. 8

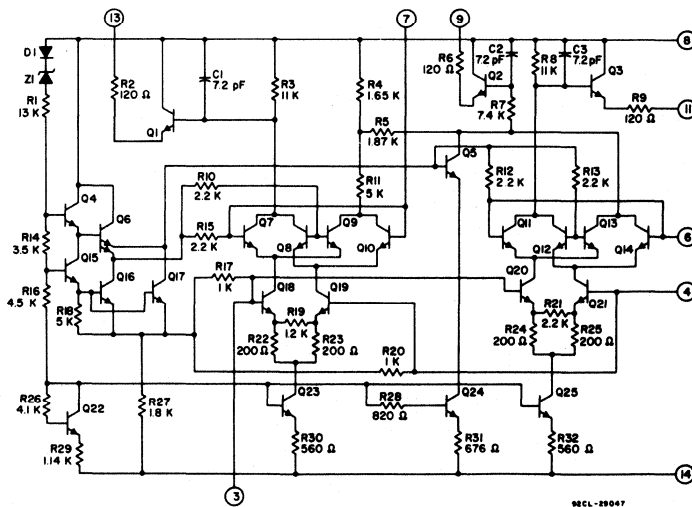


Fig. 2 — Schematic diagram for CA3172E.

ELECTRICAL CHARACTERISTICS, at $T_A = 25^\circ C$ and $V^+ = +24 V$ unless otherwise specified

CHARACTERISTICS	SYMBOLS	SPECIAL TEST CONDITIONS	LIMITS CA3172G			UNITS
			MIN.	TYP.	MAX.	

Static Characteristics^a

Supply Current With Output Loads	I_T	S_1 Closed	16.5	—	28.5	mA
With No Output Loads		S_1 Open	—	9	—	
G-Y, R-Y, B-Y Outputs	V_9, V_{11}, V_{13}	S_1 Closed	13	14.5	15.5	V
Chroma Inputs	V_3, V_4	S_1 Open	—	3.6	—	
Reference Subcarrier	V_6, V_7	S_1 Open	—	6.4	—	

Dynamic Characteristics^b

Demodulator Unbalance	V_9, V_{11}, V_{13}	$V_3 = V_4 = 0$	—	—	0.6	V_{p-p}
Maximum Color Difference Output Voltage	V_{13}	$V_3 = V_4 = 0.35 V_{p-p}$	5	—	—	V_{p-p}
Chroma Input Sensitivity	V_3	Adjust e_c for 5.0 V_{p-p} @ term No. 13 (B-Y)	—	0.2	0.35	
R-Y Output Ratio	V_{11}		—	0.95	—	
G-Y Output Ratio	V_9		—	0.32	—	
V_{DC} Difference Between any two Output Terminals	$ V_9 - V_{11} $ $ V_9 - V_{13} $ $ V_{11} - V_{13} $		$e_c = 0$	—	—	0.6
Input Impedance Reference Subcarrier	$R_i, 6, 7$ $C_i, 6, 7$		—	1.7	—	k Ω
			—	6	—	pF
Input Impedance at Chroma Inputs	$R_i, 3, 4$ $C_i, 3, 4$		—	0.95	—	k Ω
			—	6	—	pF
Output Resistance	$R_o, 9, R_o, 11, R_o, 13$		—	180	—	Ω

^a Test circuit Fig. 3

^b Test circuit Fig. 4

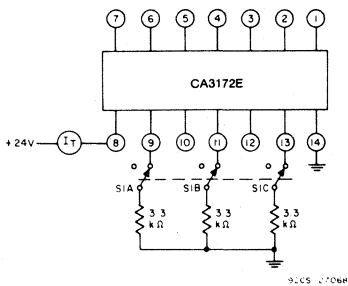


Fig. 3 - Static characteristics test circuit.

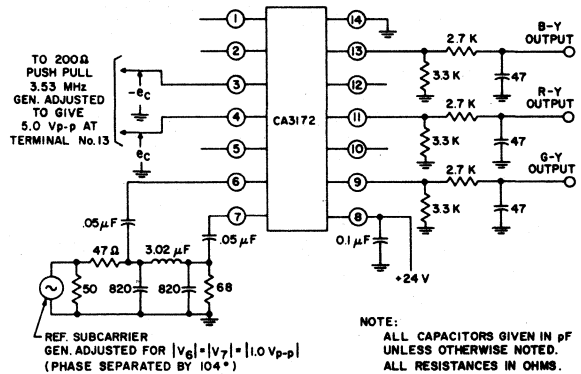
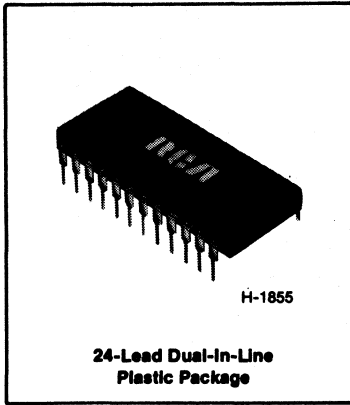


Fig. 4 - Dynamic characteristics test circuit.

CA3194E



Single-Chip PAL Luminance/Chroma Processor

System Features:

- All PAL luminance and chrominance processing circuitry on a single chip in a 24-lead plastic package
- Phase-locked subcarrier regeneration utilizing sample-and-hold
- DC controls for brightness, contrast, and color-saturation functions
- Input for average beam-current limiting
- Contrast control having excellent tracking of luma and chroma channels
- Low-impedance RGB outputs with excellent tracking for direct coupling to video driver circuitry

The RCA CA3194E* is a silicon monolithic integrated circuit designed to perform all of the signal processing functions for both the chroma and luminance signals of PAL color television receivers.

This circuit performs all the functions needed between the video detector and the video RGB output stages. DC contrast, brightness, and saturation controls and average beam limiting functions are included. The RGB buffer stages are capable of delivering 5 mA of current into the video output stages.

The CA3194E is supplied in the 24-lead dual-in-line plastic package.

*Formerly RCA Dev. No. TA10313.

Circuit Description (See Figs. 1 and 6.)

The chroma signal is externally separated from the video signal by means of a bandpass or high-pass filter and applied to pin 4. The burst is separated in the first chroma stage and applied to the synchronous detector which provides information to sample-and-hold circuits for APC (phase-locked loop), ACC (automatic chroma gain control) and identification and killing. The 4.43-MHz crystal oscillator is phase-locked to the burst and provides 0° and 90° (via an external phase shifter) carriers to the chroma demodulators. The burst and chroma amplitude at the output of the first chroma amplifier is kept constant by the automatic gain control.

The second chroma stage provides saturation control (pin 3) which tracks the contrast control in the luminance channel. This stage is also used for color killing.

MAXIMUM RATINGS, Absolute-Maximum Values

DC SUPPLY VOLTAGE AND CURRENT:

Pin 12 Voltage Range	11 Min. to 13 Max. V
Pin 12 Current Range	45 Typ. to 60 Max. mA

DEVICE DISSIPATION:

Up to $T_A=+55^\circ\text{C}$	825 mW
Above $T_A=+55^\circ\text{C}$,	Derate linearly at 8.7 mW/°C
θ_{JC} Max.=115°C/W, T_J Max.=150°C	

AMBIENT TEMPERATURE RANGE:

Operating	-40 to +85°C
Storage	-65 to +150°C

LEAD TEMPERATURE (DURING SOLDERING):

At distance 1/16 ± 1/32 in. (1.59 ± 0.79 mm) from case for 10 s max.	+265°C
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CA3194E

TERMINAL VOLTAGE AND CURRENT RATINGS

Terminal	Voltage* - V		Current - mA	
	Min.	Max.	I _{IN}	I _{OUT}
1	—	—	—	—
2	0	13	0	30
3	0	8	10	—
4	0	5	—	—
5	0	Note	—	—
6	—	—	0.1	0.5
7	0	Note	—	—
8	0	Note	—	—
9	0	8	—	—
10	0	8	—	0.7
11	0	13	—	10
12	0	13	—	—
13	0	12	—	—
14	0	5	—	1.5
15	0	5	—	1.5
16	0	13	—	10
17	0	13	—	10
18	0	13	—	10
19	0	Note	—	—
20	0	5	—	—
21	0	Note	—	—
22	0	8	—	—
23	0	5	—	—
24	0	12	—	—

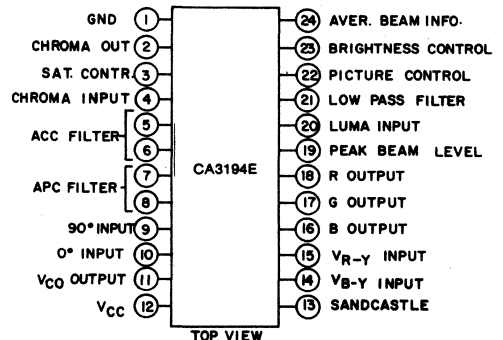
NOTE:

The maximum should not exceed the V_{CC} voltage.
 *Voltage with respect to Terminal 1 for V_{CC} (Terminal 12)
 of 12 V ± 10%.

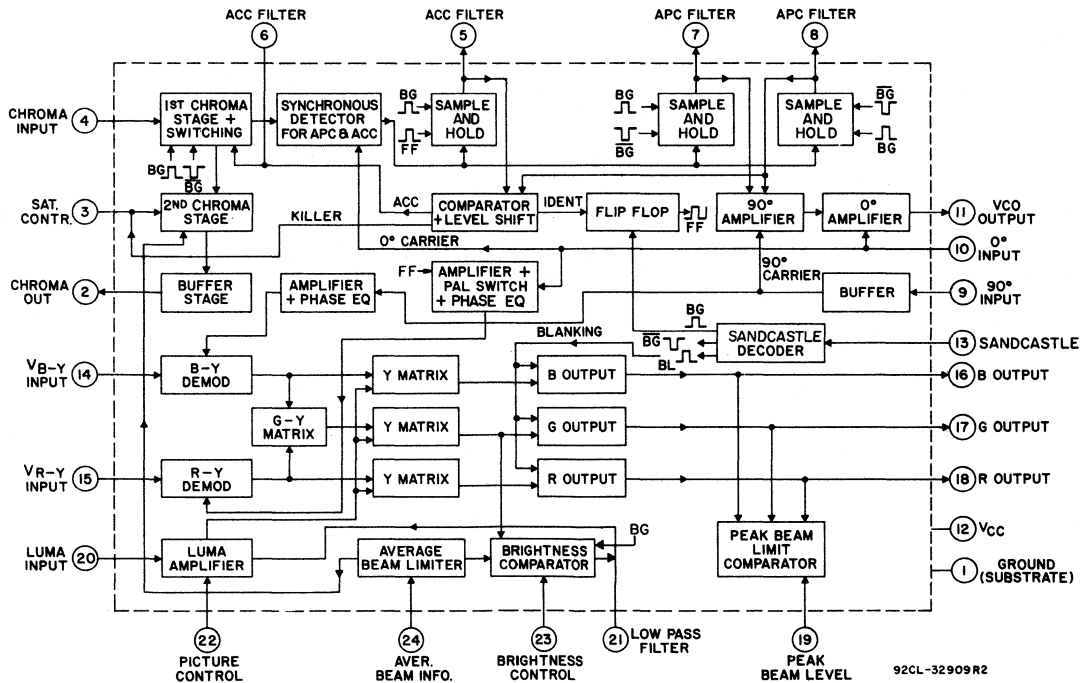
A buffer stage drives the external PAL delay line. The separated U and V signals are applied to pins 14 and 15, respectively, and demodulated. A standard G-Y matrix is included on the chip.

The luminance signal passes through the subcarrier trap and through the luminance delay line and enters the chip at pin 20. Contrast and brightness control is provided before the luminance signal is combined with the color beam difference signals in the Y matrix. Average and peak beam limiting circuits are controlled from pins 24 and 19.

TERMINAL ASSIGNMENT



92CS-33097



92CL-32909R2

Fig. 1 - Block diagram.

Linear Integrated Circuits

CA3194E

ELECTRICAL CHARACTERISTICS at $T_A=25^\circ\text{C}$, $V_{CC}=12\text{ V}$, $V_S=2.85\text{ V}$

$V_C=2.85\text{ V}$, $V_{AB}=V_{PB}=V_{CC}$, V_B adjusted for $V_{18}=6.3\text{ V}$,

C_X adjusted for $F_{OSC}=4.43361875\text{ MHz}$, Sandcastle: $V_{BQ}=8.0\text{ V}$,

$V_{BLANK}=3.5\text{ V}$ -Burst Gate centered on Burst.

These conditions exist except as otherwise noted. See Fig. 5 for test circuit.

CHARACTERISTIC	TEST CONDITIONS	TYPICAL VALUE	UNITS
LUMINANCE SECTION			
Input Impedance-Term. 20		6 5	k Ω pF
Luminance Channel Input Voltage	Luma Input Signal=30% Sync	0.5	V_{p-p}
Bandwidth of Luminance Channel	Luma Input Signal: $0.5 V_{p-p}$ (30% Sync) modulated CW Adj. modulation frequency for -3 dB at color outputs	8	MHz
Brightness Control Range-Term. 23	For control characteristics, See Fig. A	0 - 3.5	V dc
Output Black Level: Range	Luma Input Signal: $0.5 V_{p-p}$ (30% Sync) V_B 0 - 5 V	5.9 - 9.7	V dc
Offset	Measured at Pin 18 black level. See Fig. A.	0.6 Max.	
Contrast Control Range-Term. 22	Luminance input: $0.5 V_{p-p}$ (30% Sync), for control characteristics. See Fig. B.	0 - 5	V dc
Luminance Gain Control Range	Luminance Input: $0.5 V_{p-p}$ (30% Sync), $V_C=0.5 - 5\text{ V}$ measure Pin 18 black level to maximum white level. See Fig. C.	32	dB
RGB Output Swing	Luminance Input: $0.5 V_{p-p}$ (30% Sync), $V_C=5\text{ V}$, read black level to peak white. See Fig. D.	4	V_{p-p}
CHROMINANCE SECTION			
Input Impedance-Term. 4	See Fig. E.	4.5 5	k Ω pF
Chroma Channel Input Voltage	Chroma	220	mV_{p-p}
	Burst	100	mV_{p-p}
ACC Range		+6 - -20	dB
Input Burst Level for Kill	Adjust chroma input Pin 4 until Pin 2 $\leq 25 mV_{p-p}$. Measure Burst level at Pin 4.	10*	mV_{p-p}
Contrast Control Chroma/Luma Tracking	Chroma Input: Burst=100 mV_{p-p} Chroma=220 mV_{p-p} Luminance Input: $0.35 V_{p-p}$ V_S adjusted for Chroma at Pin 18=2 V_{p-p} V_C is adjusted for luminance at Pin 18=2 V_{p-p} . V_C is again adjusted for luminance of +6 and -9 dB. Then read chroma percentage difference. See Fig. F.	± 5	%
Saturation Control Range-Term. 3	For control characteristic, see Fig. G.	0 - 5	V dc
Max. Chroma Output Voltage-Term. 2	Chroma Input: Burst=100 mV_{p-p} Chroma=220 mV_{p-p} . Adjust V_C and V_S for max. Pin 2 output.	2.5	V_{p-p}

*If a different value is desired, see the Threshold Adjustment Circuit of Fig. 3.

TV/CATV Circuits CA3194E

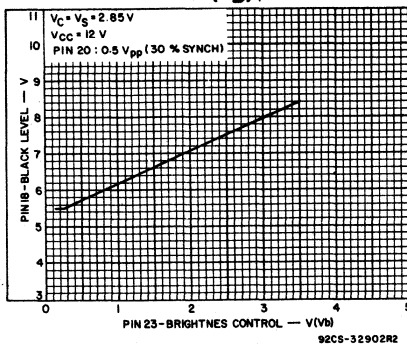
CHARACTERISTIC	TEST CONDITIONS	TYPICAL VALUE	UNITS
OSCILLATOR SECTION			
Pull-In Range	Chroma Input: Burst=100 mV _{p-p} Chroma=220 mV _{p-p} . Adjust C _X for HI/LO fOSC without Chroma signal. Apply signal to lock.	±500	Hz
Static Phase Error		2	DEG/100 Hz
DEMODULATOR SECTION			
R-Y Demodulator Conversion Gain	Chroma Input: Burst=100 mV Chroma=220 mV _{p-p} , V ϕ . Adjust V _C for V18=1 V. Read V15. Calculate V18/V15.	10	Ratio
B-Y Demodulator Conversion Gain	Chroma Input: Burst=100 mV _{p-p} , U ϕ . Read V16 and V14. Calculate V16/V14. V _C remains as for R-Y gain	18	Ratio
G-Y/B-Y Matrix Ratio	Chroma Input: Burst=100 mV _{p-p} , Chroma=220 mV _{p-p} , U ϕ read V17 and V16. Calculate V17/16. V _C remains as above.	0.2	Ratio
G-Y/R-Y Matrix Ratio	Chroma Input: Burst=100 mV _{p-p} Chroma=220 mV _{p-p} , V ϕ . Read V17 and V18. Calculate V17/18. V _C remains as above.	0.5	Ratio
Sub-Carrier and Harmonic Content at Outputs	No Chroma or Luma Input. Read residual carrier at outputs.	30	mV _{p-p}
SANDCASTLE PULSE			
Horizontal and Vertical Blanking Pedestal		2 - 5	V
Burst Gate Pulse		6.5 - V _{CC}	V

NOTE:

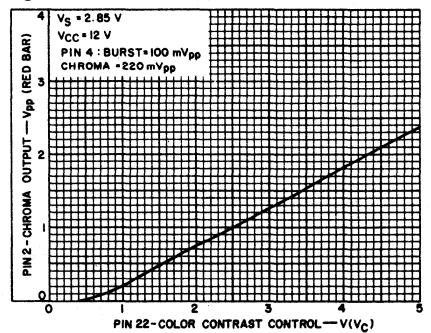
Use of the circuit of Fig. 4 is suggested to prevent increased color saturation at low level RF signals. The reference voltage can be adjusted by changing the values of the voltage divider.

TYPICAL CHARACTERISTICS (Refer to Fig. 5 for Test Circuit)

A. BRIGHTNESS CONTROL (V_B)



Measured at Pin 18 output terminal.



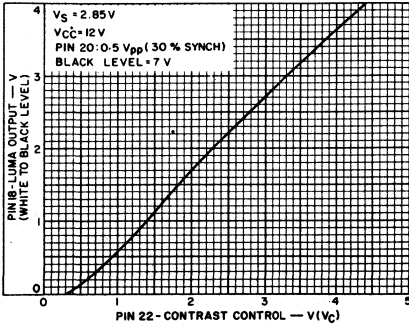
Measured at 2nd chroma amplifier output terminal.

Linear Integrated Circuits

CA3194E

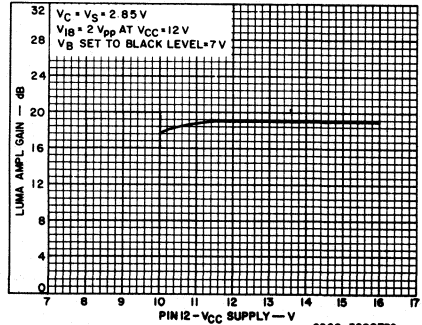
TYPICAL CHARACTERISTICS (Cont'd)

B. CONTRAST CONTROL (V_C)



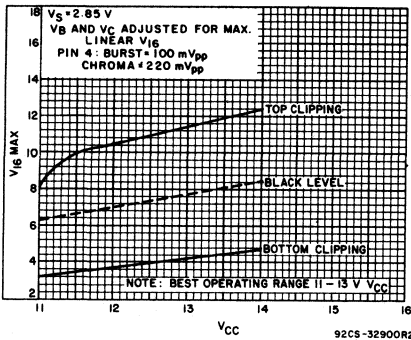
Measured at Pin 18 output terminal.

C. LUMA GAIN VS. SUPPLY VOLTAGE (V_{CC})

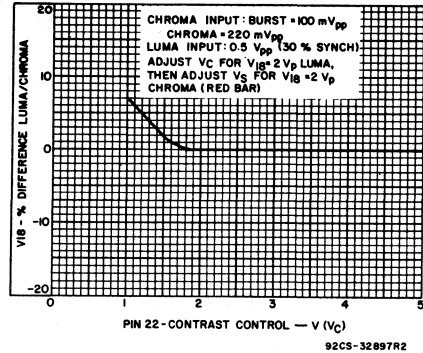


Measured at luma amplifier output terminal.

D. LINEAR OPERATING RANGE AS A FUNCTION OF V_{CC}

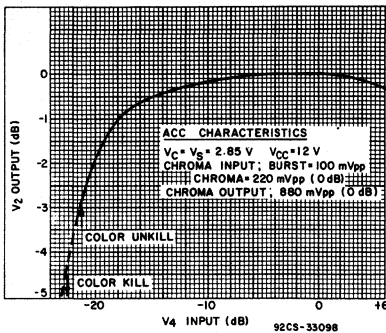


Measured at Pin 16 output terminal.

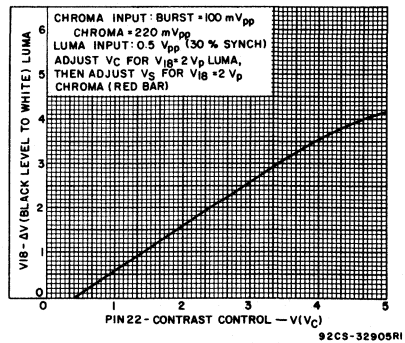


Measured at Pin 18 output terminal.

E. ACC CHARACTERISTICS



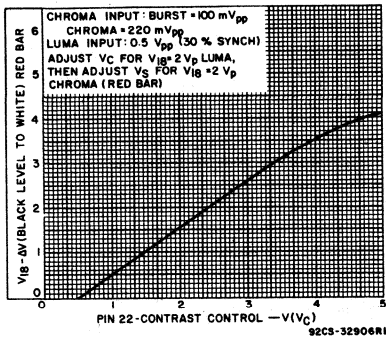
Measured at Pin 2 output terminal.



Measured at Pin 18 output terminal.

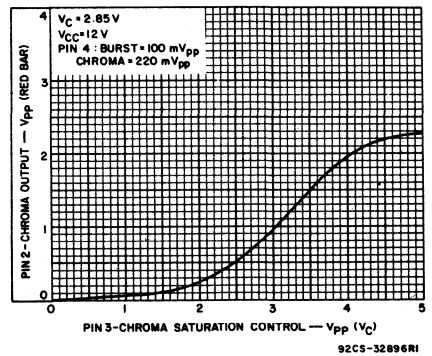
TYPICAL CHARACTERISTICS (Cont'd)

F. LUMA/CHROMA TRACKING WITH CONTRAST CONTROL



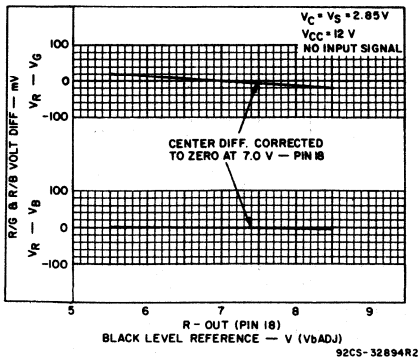
Measured at Pin 18 output terminal.

G. SATURATION CONTROL (V_s)



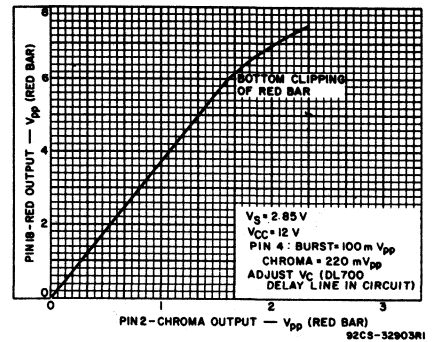
Measured at chroma amplifier output terminal Pin 2.

H. DIFFERENTIAL BLACK-LEVEL TRACKING



Measured at RGB output terminals.

I. PIN 18 OUTPUT VS. PIN 2 VOLTAGE

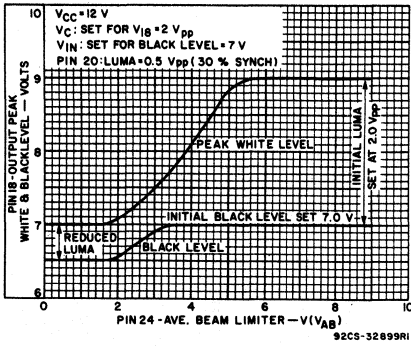


Measured at chroma output terminals and R output.

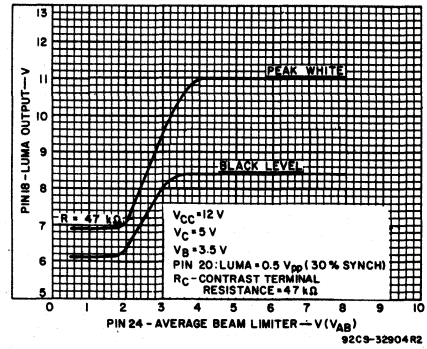
Linear Integrated Circuits

CA3194E

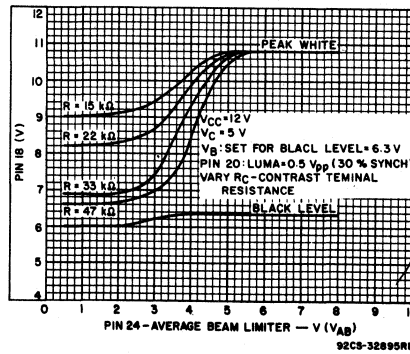
J. AVERAGE BEAM LIMITER (V_{AB})



Measured at Pin 18 output.



Measured at Pin 18 output.



Measured at Pin 18 output.

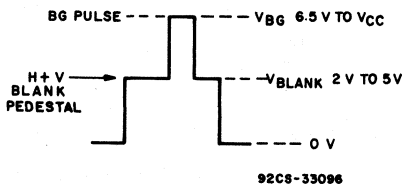


Fig. 2 - Sandcastle input waveform.

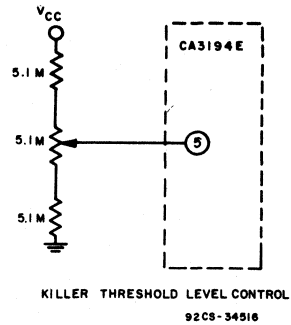


Fig. 3 - Killer-threshold level control.

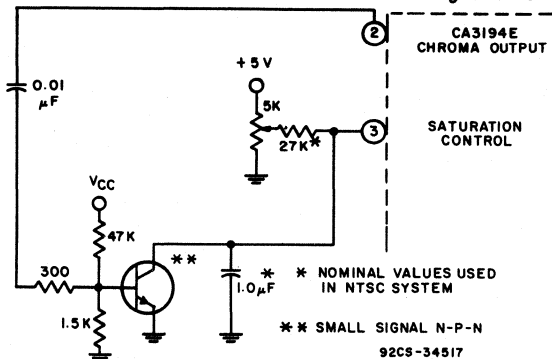
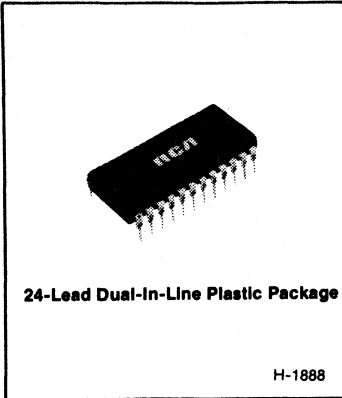


Fig. 4 - External overload detector.



Single Chip TV Chroma Processor/Demodulator

System Features

- All chroma processing and demodulating circuitry on a single chip in a 24-lead plastic package
- Phase-locked subcarrier regeneration
- Linear dc controls for chroma gain and tint
- Defeatable dynamic "flesh correction"
- Three color-difference demodulators
- First chroma amplifier with ACC control and killer sensing
- Second chroma amplifier with gain control and color killer
- Operates from +12 V
- An input (Pin 20) is provided that can be used as a variable or fixed voltage source for dc level adjustment of the R-Y, B-Y, and G-Y outputs

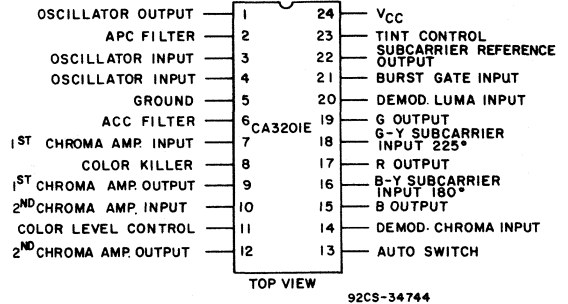
The RCA-CA3201E* is a monolithic silicon integrated circuit that performs the complete chroma processor and demodulating functions for color TV. The single chip contains all the features of the CA3158* chroma processor and the CA3145§ chroma demodulator.

The CA3201E is supplied in a 24-lead dual-in-line plastic package.

*Formerly RCA Developmental No. TA10660.

*The CA3158 is described in RCA data bulletin File No. 1170.

§The CA3145 is described in RCA data bulletin File No. 1175.



TERMINAL DIAGRAM

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE	15 V
OPERATING SUPPLY-VOLTAGE RANGE	10.8 to 13.2 V
DEVICE DISSIPATION:	
Up to T _A =55°C	1.25 W
Above T _A =55°C	Derate linearly at 13.3 mW/°C
AMBIENT TEMPERATURE RANGE:	
Operating	-40 to +85°C
Storage	-65 to +150°C
LEAD TEMPERATURE (During Soldering):	
At distance 1/16 ± 1/32 in (1.59 ± 0.79 mm) from case for 10 seconds max.	+265°C

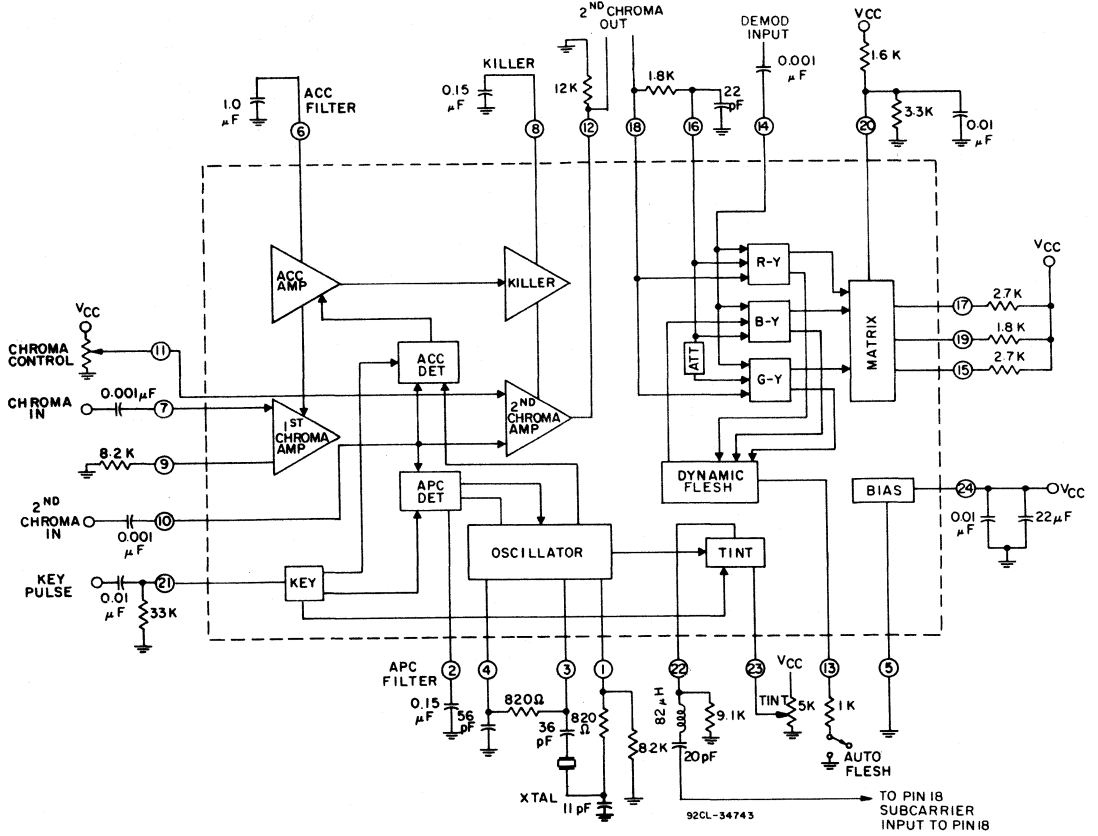


Fig. 2 - Functional block diagram of the CA3201E (see Figs. 3, 4, 7, 8 and 9).

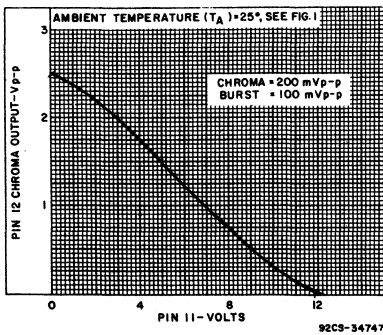


Fig. 3 - Typical saturation control vs. chroma output.

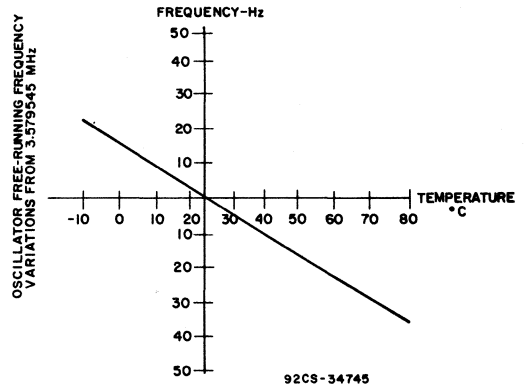


Fig. 4 - Typical oscillator frequency-temperature drift. (IC subjected to temperature only.)

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CA3201E

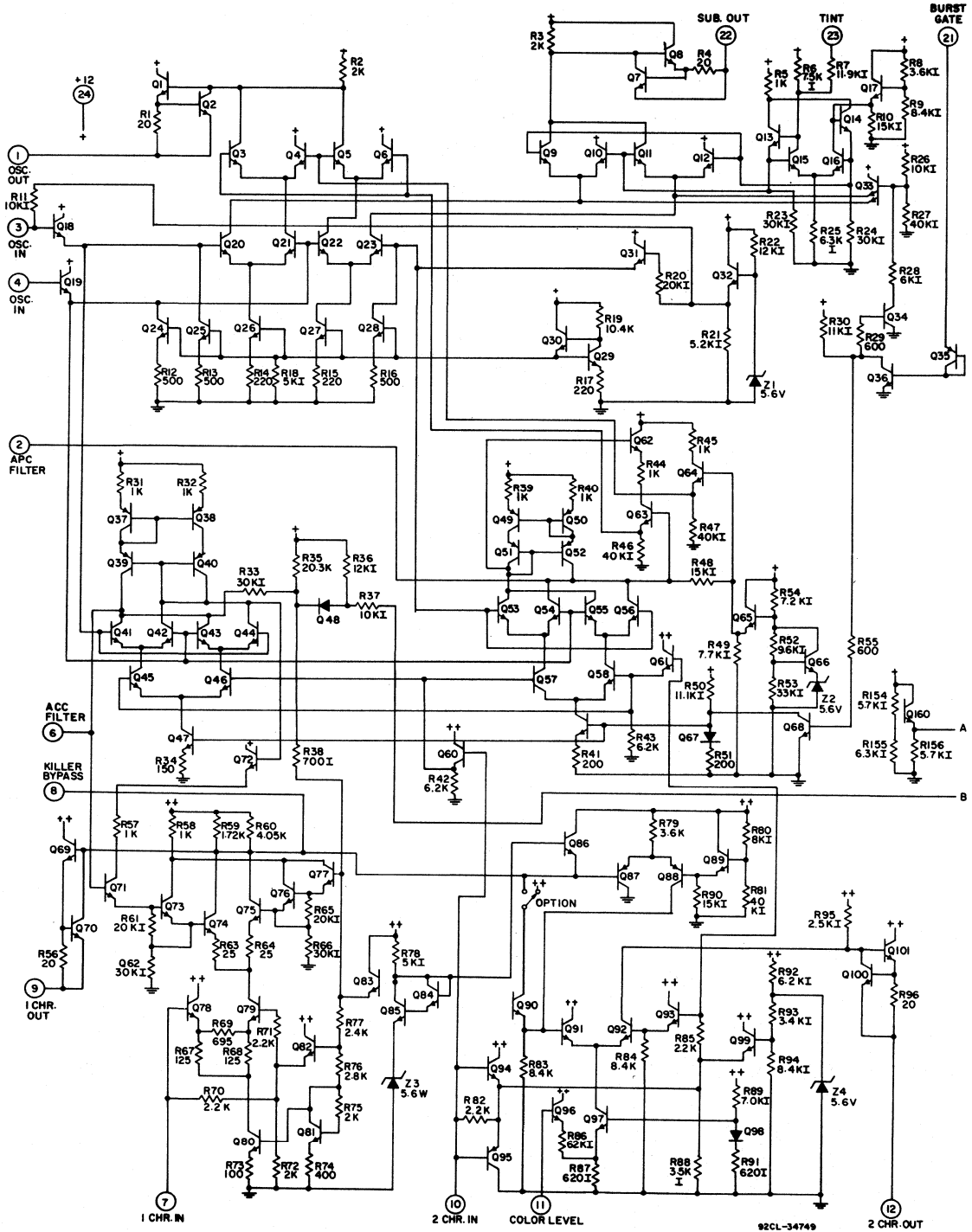


Fig. 5 - Schematic diagram of the CA3201E (Cont'd).

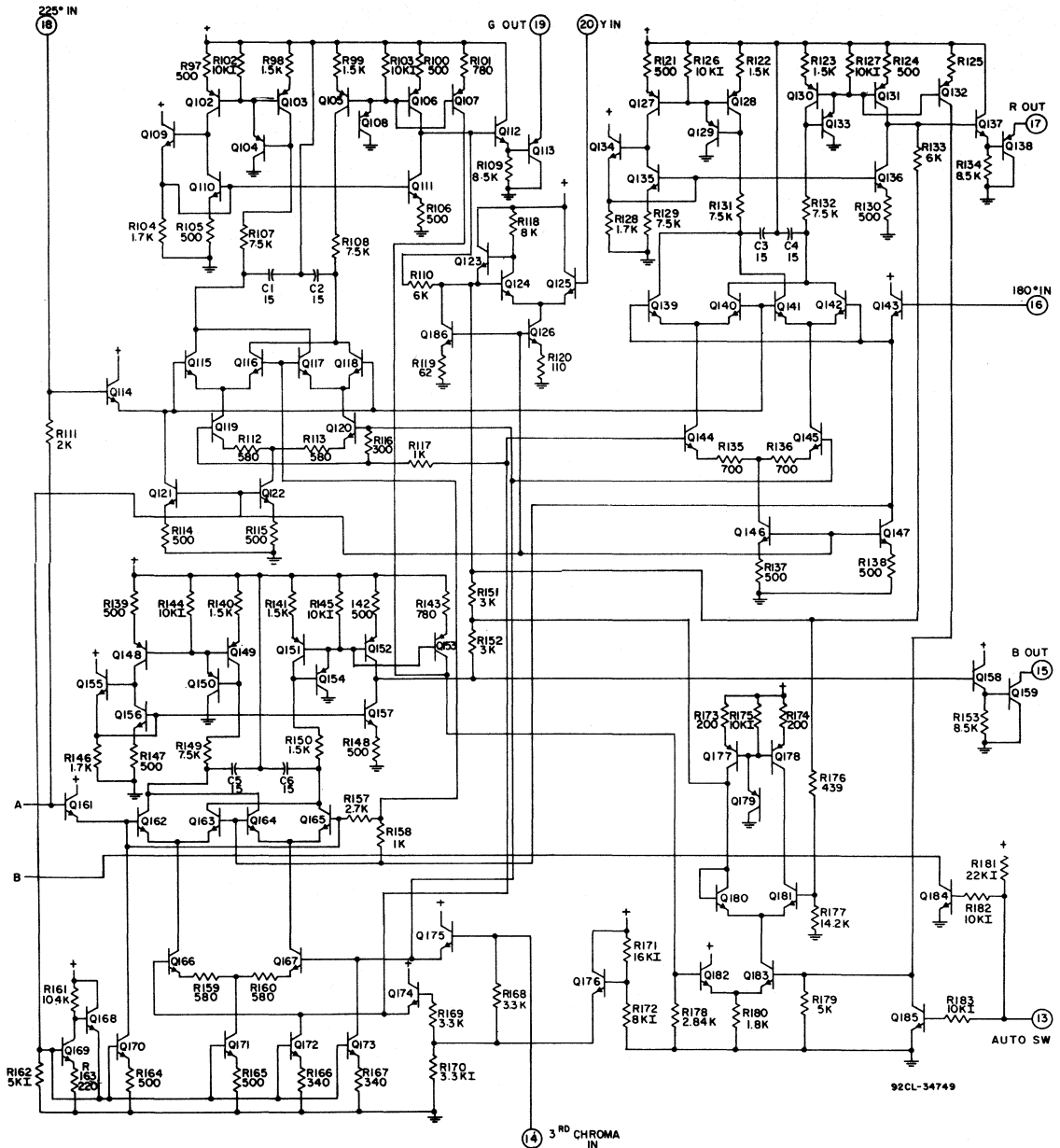


Fig. 5 - Schematic diagram of the CA3201E (Cont'd).

Circuit Description

The chroma input to pin 7 is amplified and, depending on the ACC voltage, is applied to pin 9. When the ACC voltage demands full gain to R59 and pin 9, the actuating signal for the color killer is developed on R60. The signal from pin 9 is applied to pin 10 for use by both the second chroma amplifier and the phase detectors. The signal swing at pin 10 is limited by Q94 and Q95. The gain of the second chroma amplifier to pin 12 is controlled by pin 11 voltage.

The signal at pin 10 is applied to the two phase detectors at Q46 and Q57. The current sources to the two phase detectors are turned on only during burst time as determined by the burst-gate input at pin 21. The oscillator signals for the phase detectors are derived from the oscillator signals at pin 3 and pin 4 and the quadrature phase difference is achieved the same way as in the oscillator. Both phase detectors convert their balanced outputs to single-ended outputs by use of current mirrors. The ACC voltage is

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CA3201E

developed across R33 and is filtered by an external capacitor at pin 6. ACC action is delayed by the small voltage applied to R33 by divider R35 and R38 (auto mode off). This delay offset is modified by R36 and Q48 when the "auto mode" switch is on. Because the duty cycle of the phase detectors is small, the base current of the ACC circuit (emitter follower Q71) is a drain on the ACC filter capacitor, and Q72 provides a compensating base current to the other side of the mirror. A similar circuit is used for the APC detector.

The external circuit of the oscillator, when tuned properly, provides a 90-degree phase shift from pin 1 to pin 3 and an additional 45-degree phase shift between pin 3 and pin 4. The voltage at pin 4 is shifted 45 degrees by an RC phase shifter and this voltage is applied to a series-tuned circuit comprised of a crystal and capacitor to pin 3, a resistor between pin 3 and pin 4, and a capacitor between pin 4 and ground. With the same current flowing through the resistor and capacitor, the voltage across the capacitor (pin 4 to

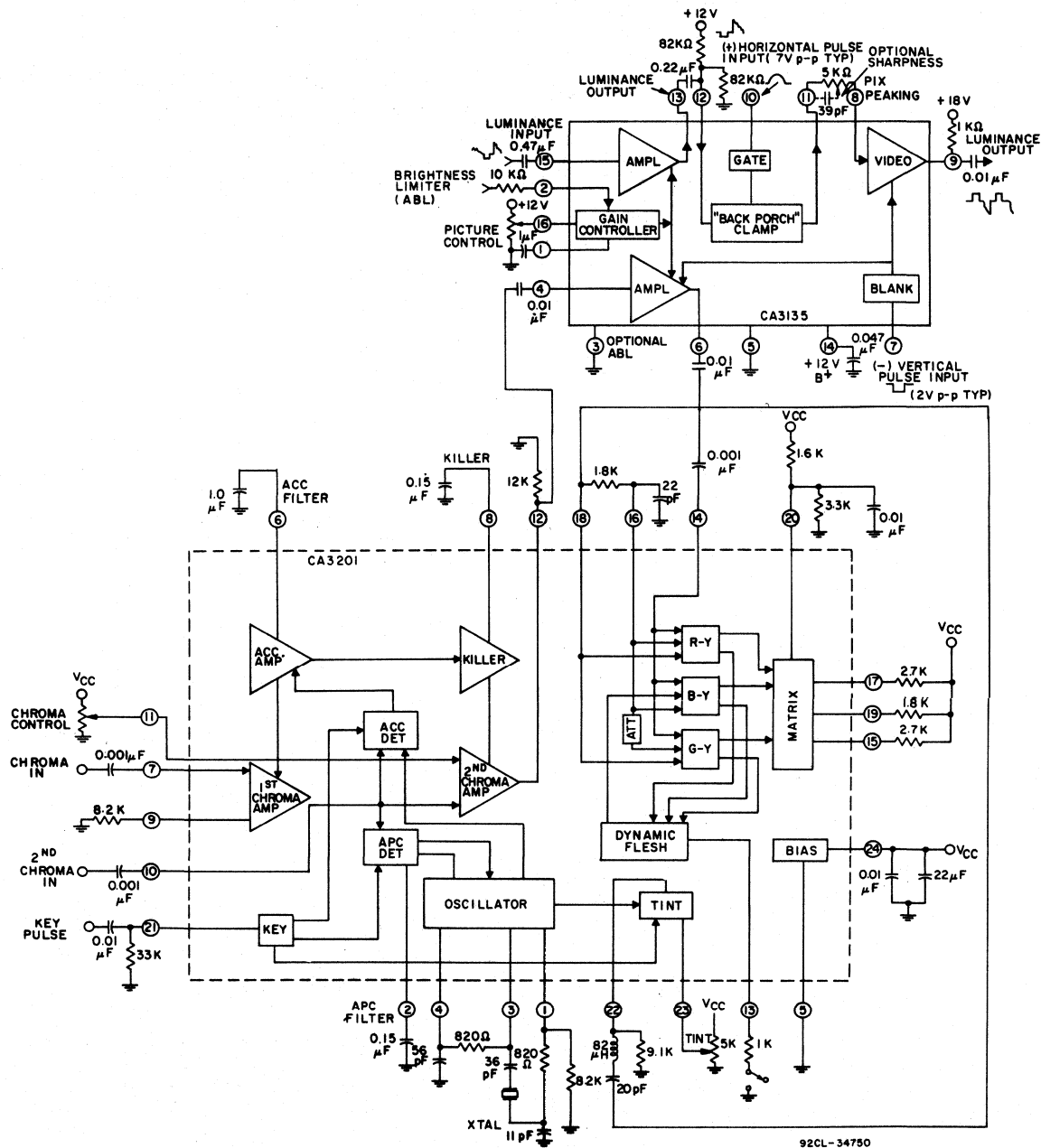


Fig. 6 - Typical two-package chroma-luma system for color TV receivers utilizing the CA3201E and CA3135.

CA3201E

ground) is in quadrature with the voltage across the resistor (pin 3 to pin 4). The differential amplifier, Q22 and Q23, is switched in quadrature with the differential amplifier, Q20 and Q21. Although the ac voltage amplitudes are different in all these places, the differential amplifiers are switched hard, and their current sources determine the amplitudes of currents combined in the oscillator. The combination can be varied by the APC control voltages to give a total phase of 90 degrees.

The complements of the oscillator quadrature currents are applied to another dc-controlled combination circuit (Q9-Q12) for tint control.

The CA3201E uses three color demodulators. The 3.58-

MHz reference signals at 180 degrees and 225 degrees are matrixed to obtain the three phases for the demodulators. A "switchable automatic flesh" system modifies the B-Y demodulator out for fleshtone correction. The three demodulators are identical except for gain. The differential output current from the demodulators are filtered and processed to single-ended currents. Current mirrors provide a current gain of three and a current output for the auto-flesh circuit.

The auto-flesh comparator, Q182 and Q183, sees the R-Y signal on the Q183 side (when pin 13 is grounded—auto switch on) and the sum of the G-Y and B-Y signals on the other side. The auto-flesh output current is applied to the mid-point of the B-Y demodulator load.

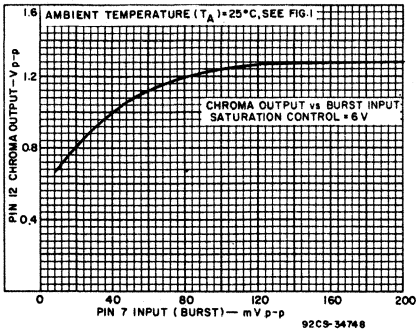


Fig. 7 - Typical ACC curve (burst-chroma ratio - 0.5).

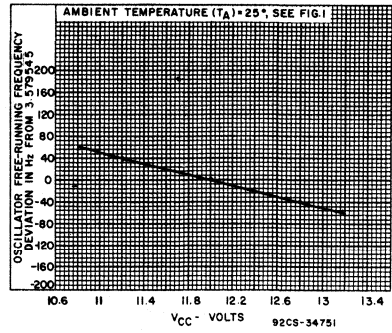


Fig. 8 - Typical oscillator frequency deviation vs. VCC.

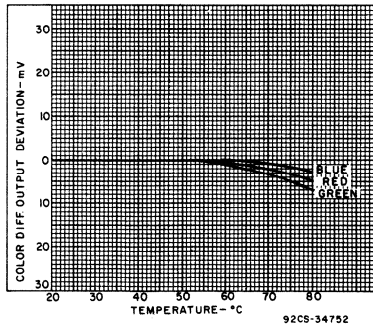
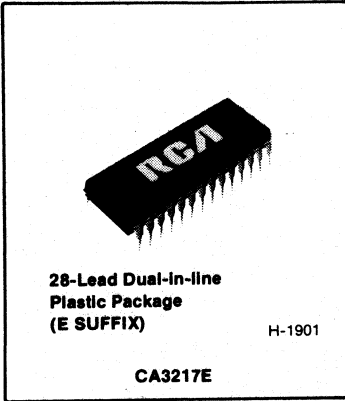


Fig. 9 - Typical dc output deviation vs. temperature.

CA3217E



Single Chip TV Chroma/Luminance Processor

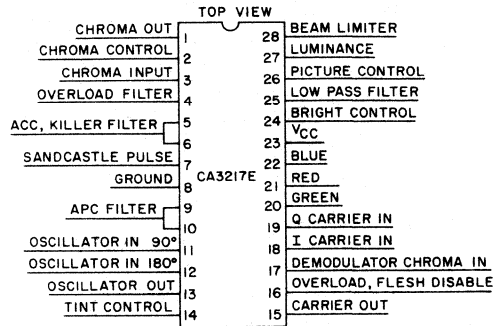
System Features:

- All chroma processing and demodulating circuitry on a single chip in a 28-lead plastic package
- Phase-locked subcarrier regeneration utilizing sample-and-hold techniques
- Supplementary ACC with overload detector to prevent over saturation of the picture tube
- Linear dc controls for chroma gain and tint
- Dynamic "flesh correction" - corrects purple and green flesh colors without affecting primary colors
- Balanced chroma demodulators with low output impedance for direct coupling
- Internal rf filtering
- Requires few external components
- Automatic beam limiter
- Chroma luminance tracking picture control

The RCA CA3217E* is a monolithic silicon integrated circuit. It contains all the required circuits functions between the video detector and the picture tube RGB driver stages of a color television receiver. The CA3217E decodes the chrominance signals and then produces three different color signals that are internally combined with the luminance to develop the RGB signals. The picture saturation, hue and brightness DC controls are externally adjustable by the viewers. The AFPC, ACC, Dynamic flesh control, Beam limiting and Gate black level (Brightness) control are servo loops used to stabilize the RGB output and reduce frequent manual adjustment. The automatic beam limiter circuit reduces picture contrast and brightness to prevent excessive drive output at the picture tube.

The CA3217E is supplied in a 28-lead dual-in-line plastic package, (E Suffix).

*Formerly RCA Dev. Type No. TA10806.



92CS-34653

TERMINAL ASSIGNMENT

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE	14.0 V
Between Terms. 23 and 8	
DEVICE DISSIPATION:	1.27 W
Up to T _A = 55° C	
Above T _A = 55° C	Derate linearly at 13.3 mW/°C
AMBIENT TEMPERATURE RANGE:	
Operating	-40 to +85° C
Storage	-65 to +150° C
LEAD TEMPERATURE (During Soldering):	
At distance 1/16 ± 1/32 inch	
(1.59 ± 0.79 mm) from case	
for 10 seconds max.	+265° C

ELECTRICAL CHARACTERISTICS at T_A = 25° C

CHARACTERISTIC	TEST CONDITIONS											LIMITS			UNITS
	Test	S ₂	S ₃	S ₄	S ₅	S ₆	mV _{p-p} Chroma	mV _{p-p} Burst In	mV _{p-p} Luma	Relays Energized	Note	Min.	Typ.	Max.	
STATIC (Test 1-5)															
Dissipation	Pin 23	6.3 V	11.2 V	4.0 V	6.3 V	11.2 V						30	48	66	mA
Pin 1 Bal	XPT1	1.2 V	11.2 V	4.0 V	6.3 V	11.2 V							10.5		Vdc
Pin 3 Bal	XPT1	1.2 V	11.2 V	4.0 V	6.3 V	11.2 V							2.2		
Pin 17 Bal	XPT9	1.2 V	11.2 V	4.0 V	6.3 V	11.2 V							3.0		
Pin 13 Bal	XPT13	1.2 V	11.2 V	4.0 V	6.3 V	11.2 V							7.5		
DYNAMIC (Test 6-26)															
Oscillator Pull-in	"D"	6.3 V	11.2 V	4.0 V	6.3 V	11.2 V	25	25		K4, K7	1	-350		+350	Hz
Oscillator Level	"D"	6.3 V	11.2 V	4.0 V	6.3 V	11.2 V	0	0		K7			0.7		V _{p-p}
100% Acc	P21	Vary	11.2 V	4.0 V	6.3 V	11.2 V	125	125		K4, K7	2		1.5		%
200% Acc	P21	T8	11.2 V	4.0 V	6.3 V	11.2 V	250	250		K4, K7	3		100		
20% Acc	P21	T8	11.2 V	4.0 V	6.3 V	11.2 V	25	25		K4, K7	3		90		
Tint Center	S5	Vary	11.2 V	4.0 V	Vary	11.2 V	250	125		K4, K7	4		6.5		Vdc
R-Y Maximum	P21	11.2 V	11.2 V	6.0 V	T11	11.2 V	250	125		K1, K4, K7			6.0		V _{p-p}
Unkill	P21	11.2 V	11.2 V	4.0 V	T11	11.2 V	25	12.5		K4, K7			4.5		mV _{p-p}
Kill	P21	11.2 V	11.2 V	4.0 V	T11	11.2 V	25	2.5		K4, K7				150	
Chroma Reserver Maximum Luma	P21	11.2 V	11.2 V	4.0 V	T11	11.2 V	12.5	125		K2, K4, K7			2.0		V _{p-p}
Luma Ratio	P21	11.2 V	6.3 V	4.0 V	T11	11.2 V			125	K1, K3, K7	5		2.2		%
Linearity	P21	11.2 V	Vary	3.0	T11	11.2 V			425	K3, K7	7		4		
T19 = T19/T18	P21	11.2 V	T18	3.0	T11	11.2 V			212.5	K3, K7			50		%
4.78 MHz Response	P21	11.2 V	11.2 V	4.0 V	T11	11.2 V			125	K3, K4, K7	8	-3		3	dB
Contrast Limit 1	P24	11.2 V	11.2 V	4.0 V	T11	11.2 V			250	K3, K5, K7	9		3.9		Vdc
Contrast Limit 2	P26	11.2 V	11.2 V	4.0 V	T11	11.2 V			250	K3, K5, K7	9		8.2		
Bright Limit 1	P24	11.2 V	11.2 V	4.0 V	T11	11.2 V			250	K3, K5, K7	10		3.1		
Bright Limit 2	P26	11.2 V	11.2 V	4.0 V	T11	11.2 V			250	K3, K5, K7	10		5.6		
G-Y Ratio	P20	Vary	11.2 V	4.0 V	T11	11.2 V	250	125			11		0.33		R
B-Y Ratio	P22	T25	11.2 V	4.0 V	T11	11.2 V	250	125			11		1.20		

Notes:

- With K7 energized and frequency counter at D vary C1 for 3.579175 MHz. Then with K4 energized, check for pull-in. Repeat for frequency tuned to 3.579875 MHz. For all other tests tune to 3.579545 MHz ±10 Hz.
- Vary S2 for 1.5 V_{p-p} at Pin 21.
- % of 100% ACC.
- Adjust C1 for 3.579545 MHz ±10 Hz. Adjust S2 for 1.6V V_{p-p} at Pin 22 and 0 reference; then adjust S5 for minimum at P21. Read and record S5 voltage
- Black to White.
- T17 = T17/T16.
- Adjust S3 for 4.0 V_{p-p}.
- AC amplitude = 50 mV_{p-p} reference 15 kHz.
- Adjust beam limiter to 10.7 V.
- Adjust beam limiter to 9.8 V.
- Adjust S2 for 1.5 V_{p-p} at Pin 21, then calculate P20/P21 and P22/P21.

Linear Integrated Circuits

CA3217E

TYPICAL PERFORMANCE OF THE CA3217E

Function	Typical Data	
Nominal Supply	11.2V	
Nominal Dissipation	500 mW	
Oscillator Stability		
Supply Variation 10 ⁻¹⁴ V	5 Hz	
Variation with Temperature (ΔT = 50°C)	25 Hz	
AFPC Characteristics		
dc Loop Gain	33 Hz/degree	
Pull-in Range	±500 Hz	
ACC Characteristic		
100% Chroma Input Level	250 mV _{p-p} on red bar	
3-dB Point	at 20% nominal input level	
Hue-Control Range	100°	
Saturation-Control Range	40 dB min	
Demodulator Characteristics:	Relative Amplitude	Angle
R — Y	1.0	93°
B — Y	1.2	2°
G — Y	0.3	258°
Bandwidth (Chroma)	900 kHz	
Flesh Control	Primary control in the +1 half-plane	
Chroma Overload Control	Two levels	
Picture Control	40 dB	
Brightness Control	Black level clamped on 3 V to 5 V level	
Beam Limiting	On picture and brightness controls	
Luma Bandwidth	5 MHz min	
Sandcastle Input		
1.2 — 2.3 V	Blanking	
>3.3 V	Burst gate	
Maximum Linear Output		
R	5 V	
G	3 V	
B	3.7 V	

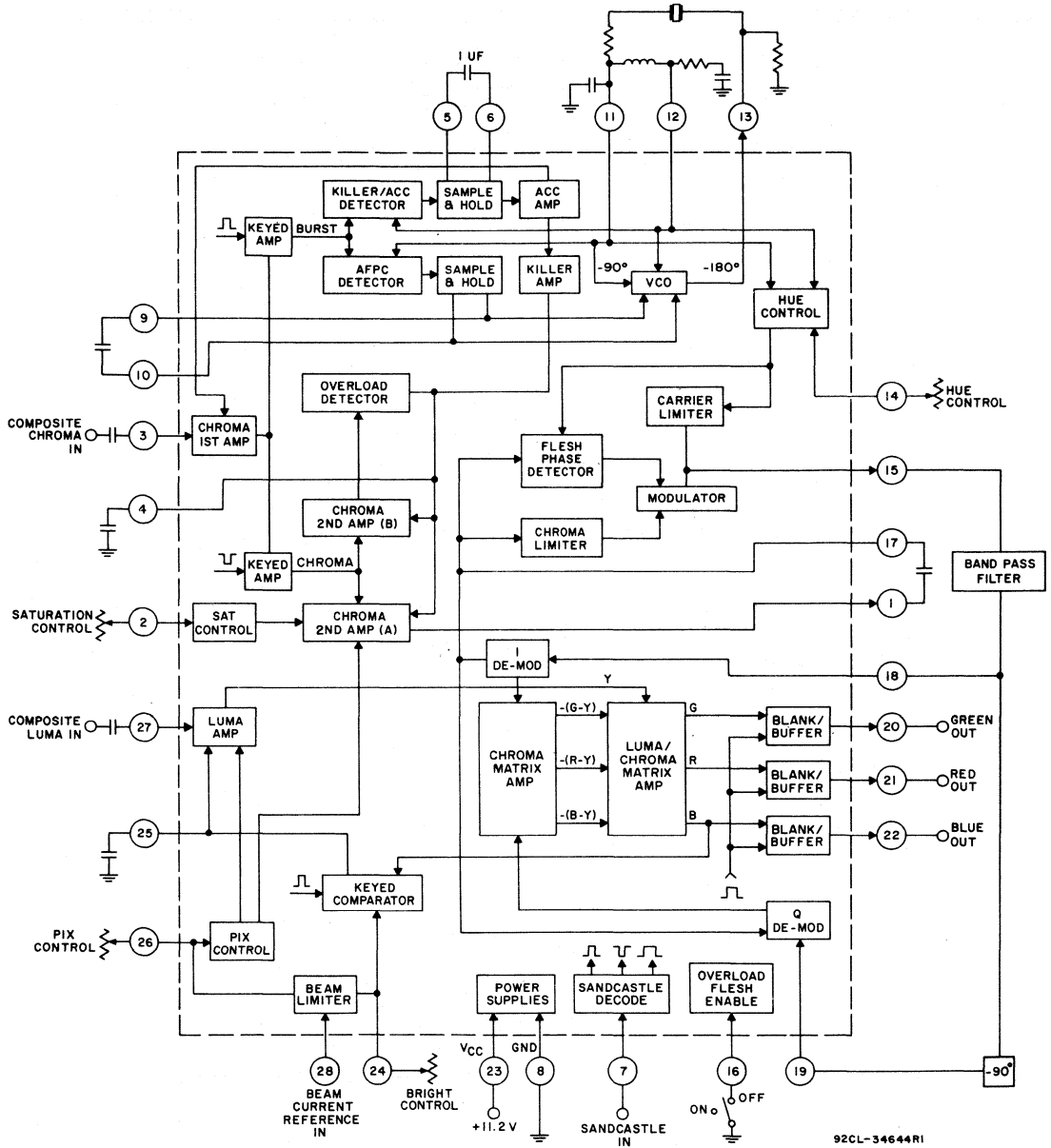


Fig. 1 - Functional block diagram of the CA3217E.

CA3217E

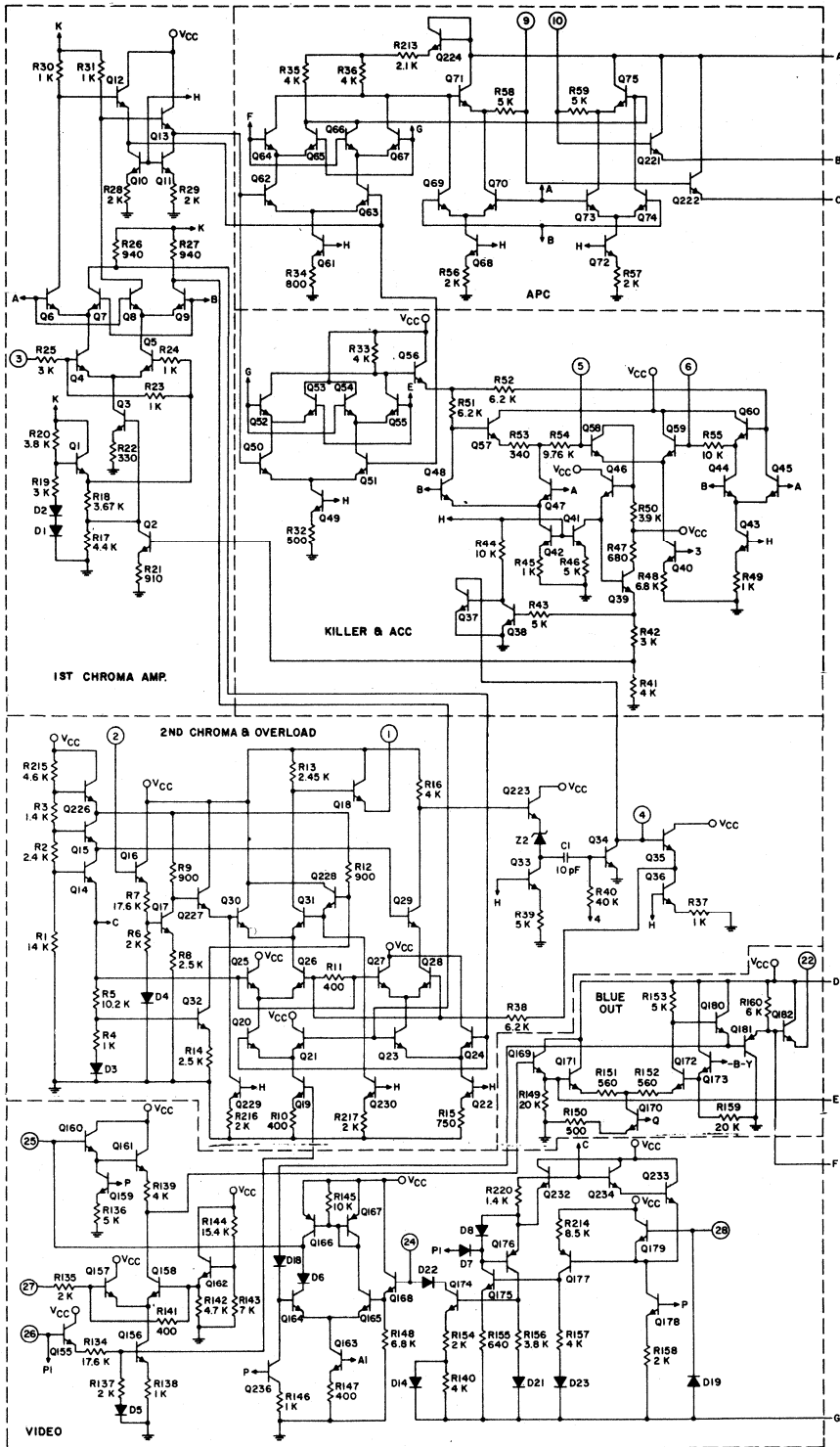


Fig. 2 - Schematic diagram of the CA3217E.
(Cont'd on next page).

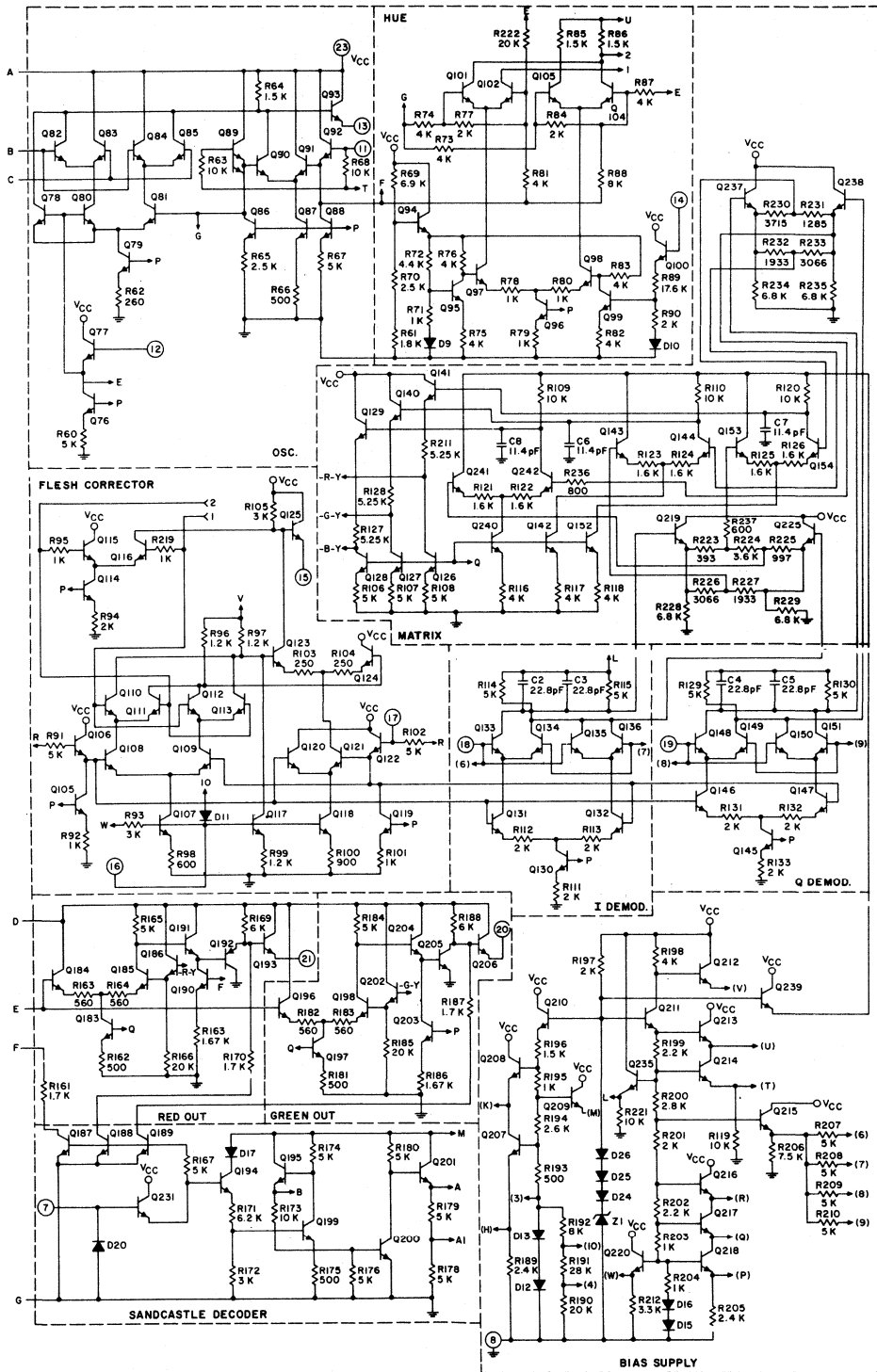


Fig. 2 - Schematic diagram of the CA3217E.
(Cont'd from previous page).

92CL-34643

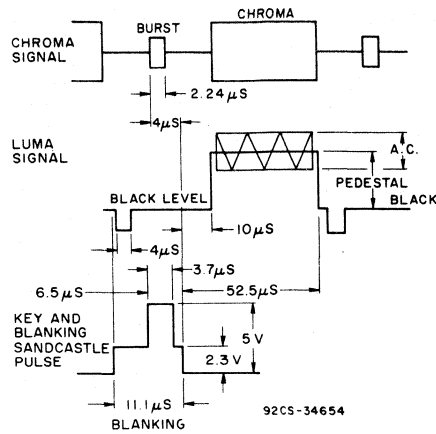


Fig. 5 - Test signals for the CA3217E.

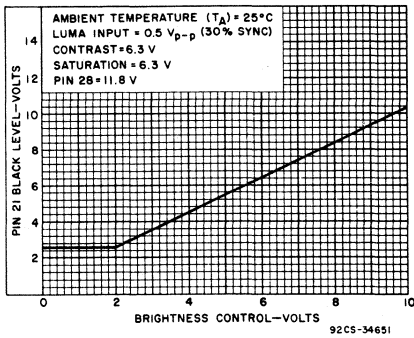


Fig. 6 - Typical P21 black level versus brightness control.

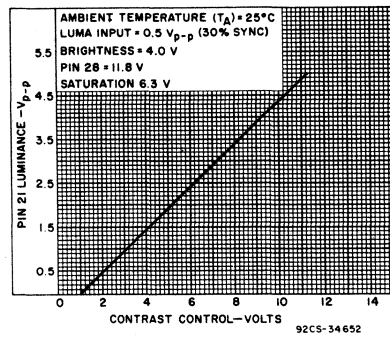


Fig. 7 - Typical P21 luminance output versus contrast control.

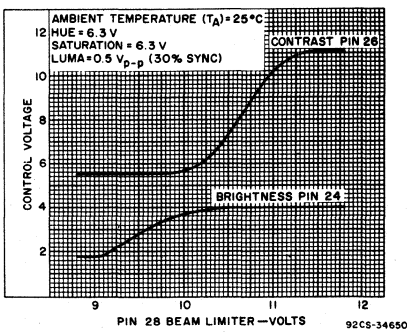


Fig. 8 - Typical beam limiter versus contrast and brightness.

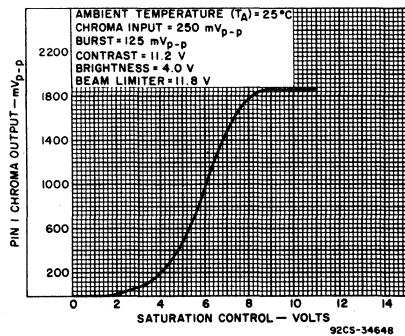


Fig. 9 - Typical P1 chroma output versus saturation control.

CA3217E

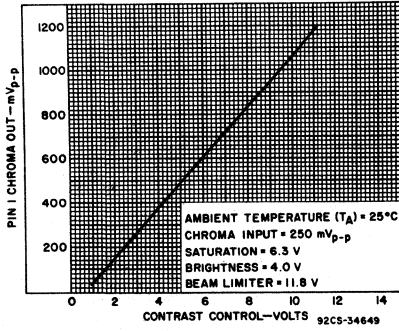


Fig. 10 - Typical P1 chroma output versus contrast control.

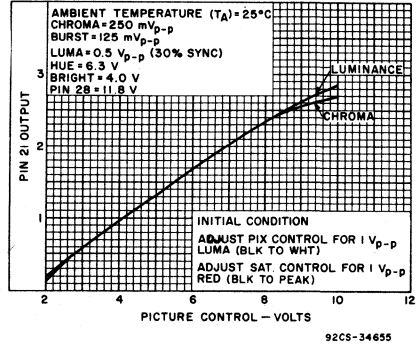
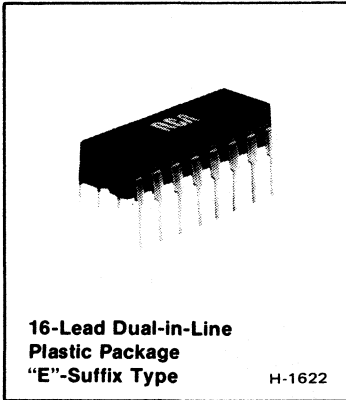


Fig. 11 - Typical luma/chroma track.



TV Chroma Amplifier/ Demodulator

Provides Complete System for Processing Chroma
When Used with RCA-CA3070 or CA3170

FEATURES:

- Excellent linearity in dc chroma gain-controlled circuit
- Improved filtering resulting in reduced 7.2-MHz output from the color demodulators
- Current limiting for short-circuit protection
- High tolerance to B+ supply variations
- High temperature coefficient stability

The RCA-CA3221E is a monolithic silicon integrated circuit chroma amplifier/demodulator with ACC, saturation control, and killer control for use in NTSC color TV receivers. It is designed to function compatibly with the CA3070 or CA3170 in a 2-package chroma system. The CA3221E is functionally identical to the industry standard

CA3121, but has a modified saturation control as well as a modified color difference matrix.

The CA3221E is supplied in the 16-lead dual-in-line plastic package.

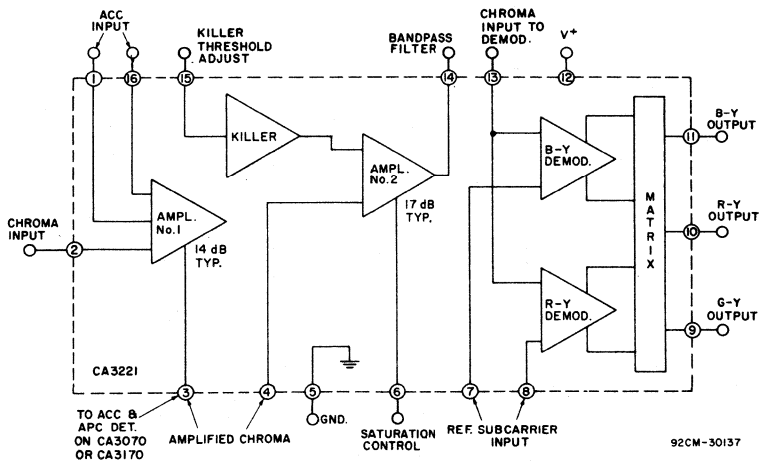


Fig. 1 — Functional block diagram of the CA3221E.

Linear Integrated Circuits

CA3221E

MAXIMUM RATINGS at $T_A = 25^\circ\text{C}$

Supply Voltage	30 V
Device Dissipation:	1 W
Up to $T_A = 55^\circ\text{C}$	
Above $T_A = 55^\circ\text{C}$	derate linearly $10.5 \text{ mW}/^\circ\text{C}$
Operating Temperature Range	-40 to $+85^\circ\text{C}$
Storage Temperature Range	-65 to $+150^\circ\text{C}$
Lead Temperature (During Soldering)	$+265^\circ\text{C}$
At distance $1/16'' \pm 1/32''$ ($1.59 \pm 0.79 \text{ mm}$) from case for 10 s max.	

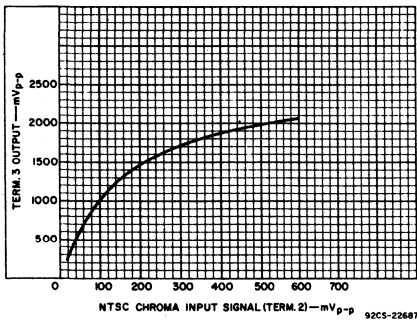


Fig. 2 - Typical ACC plot for the CA3221E when used with the CA3070.

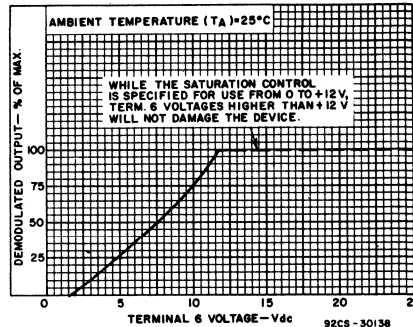
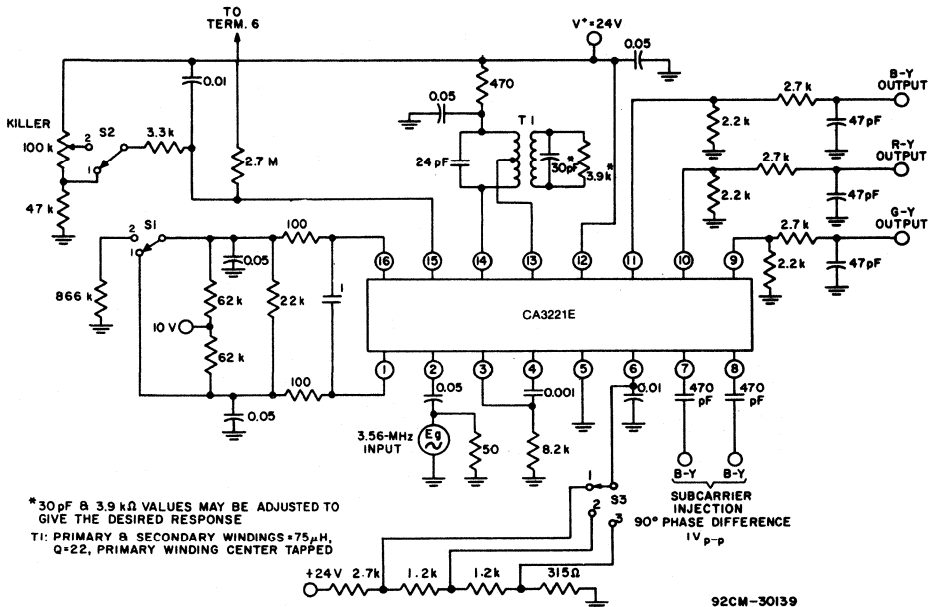


Fig. 3 - Saturation control characteristic.



NOTE:
 2.2-kΩ LOADS ONLY FOR TEST PURPOSE, 3.3-kΩ LOADS RECOMMENDED FOR APPLICATIONS.
 RESISTANCE VALUES ARE IN OHMS.
 CAPACITANCE VALUES ARE IN MICROFARADS UNLESS OTHERWISE INDICATED.

Fig. 4 - Typical characteristics test circuit for the CA3221E.

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$ and Referenced to Test Circuit (Fig. 4)

CHARACTERISTIC, TERMINAL MEASURED, AND SYMBOL	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
Supply Current, I_T	—	—	40	50	mA
Input Sensitivity, V_2	Vary E_g ; set V_{11} for 2 V RMS $S_3 = 1$	4	12	20	mV RMS
Second-Stage Sensitivity, V_4	Vary E_g ; set V_{11} for 2 V RMS $S_3 = 1$	30	53	75	mV RMS
Output Voltage (Killer off)	Switch Positions: $S_1=2, S_2=2,$ $S_3=1$ Adjust killer potentiometer until output drops	—	—	70	mV RMS
Saturation Control Characteristics: * V_{11} 50% Gain	Vary E_g ; set V_{11} for 2 V RMS with $S_3 = 1$. Set $S_3 = 2$ measure V_{11}	0.71	0.95	1.16	V RMS
0% Gain	Same as above, $S_3 = 3$	—	—	20	mV RMS
Demodulator Characteristics:					
Output Voltages, V_g, V_{10}, V_{11}	—	13.5	14.5	15.5	V
DC Output Balance (Between any 2 outputs)	—	-0.6	—	+0.6	V
Unbalance, V_g, V_{10}, V_{11}	$E_g=0$; Switch Position: $S_1=1,$ $S_2=1, S_3=1$	—	—	0.8	Vp-p
Relative Outputs— R-Y, V_{10}	Vary E_g ; set V_{11} for 2 V RMS, $S_3 = 1$	1.75	1.85	1.95	V RMS
G-Y, V_g		0.6	0.7	0.8	V RMS
Relative Phase, — R-Y, V_{10}	Vary E_g ; set V_{11} for 2 V RMS; read phase of V_{10} and V_g	—	90	—	degrees
G-Y, V_g	with V_{11} as reference	—	244	—	degrees
Max. Output Voltage, V_{11}	$E_g = 750$ mV	2.8	—	—	V RMS

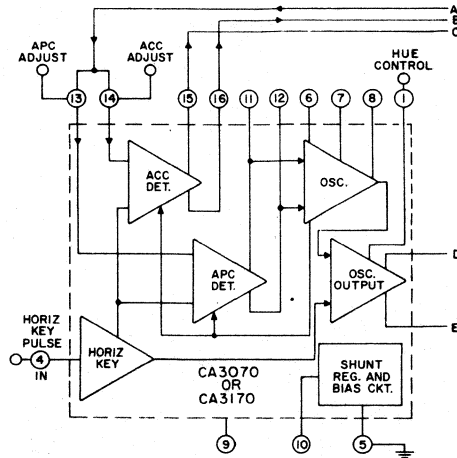
* See Fig. 3 for saturation control characteristic.

CIRCUIT OPERATION

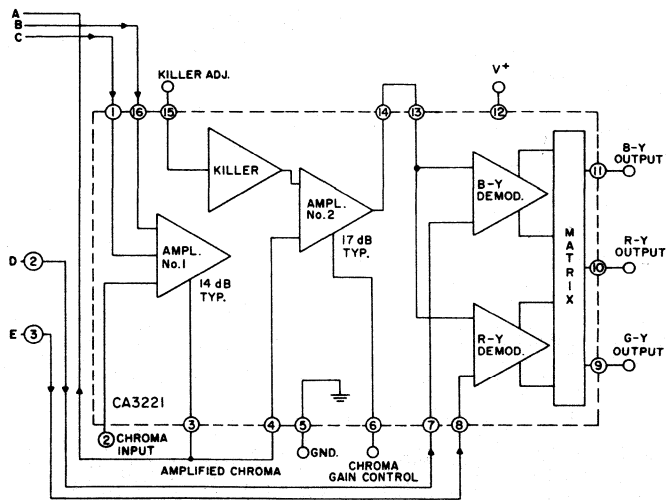
The CA3221E consists of three basic circuit sections: (1) amplifier No. 1, (2) amplifier No. 2, and (3) demodulator. Amplifier No. 1 contains the circuitry for automatic chroma control (ACC) and color-killer sensing. The output of amplifier No. 1 (Terminal 3) is coupled to the Chroma Signal Processor (CA3070 or equivalent) for ACC and automatic phase control (APC) operation and to the input of amplifier No. 2 (Terminal 4) containing the chroma gain control circuitry. The signal from the color-killer circuit in amplifier No. 1 acts upon amplifier No. 2 to greatly reduce its gain under weak signal conditions.

The output from amplifier No. 2 (Terminal 14) is applied, through a Bandpass Filter, to

the demodulator input (Terminal 13). The demodulator also receives the R-Y and B-Y demodulator subcarrier signals (Terminals 7 and 8) from the oscillator output of the chroma signal processor. The R-Y and B-Y demodulators and the matrix network contained in the demodulator section of the CA3221E reconstruct the G-Y signal to achieve the R-Y, G-Y, and B-Y color difference signals. These high-level outputs signals with low impedance outputs are suitable for driving high-level R, G, B output amplifiers. Internal capacitors are included on each output to filter out unwanted harmonics. For additional operating information and signal waveforms, refer to Television Chroma System (utilizing RCA-CA3070, CA3071, CA3072), File No. 468.



92CM-30142



92CM-30142

Fig. 6 — Simplified functional diagram of a two-package TV chroma system utilizing the CA3221E and CA3070 or CA3170.

Linear Integrated Circuits

CA3221E

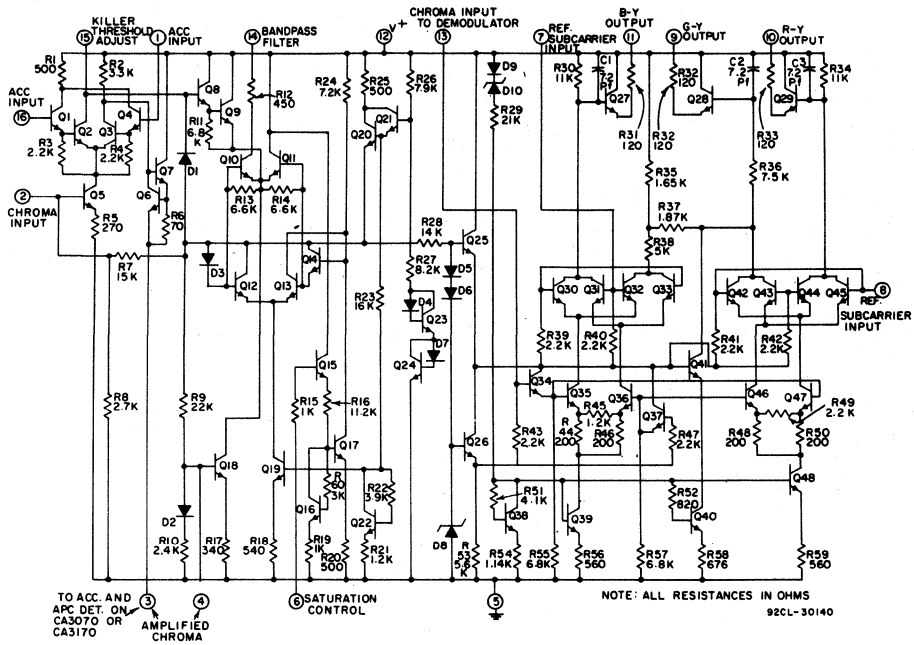
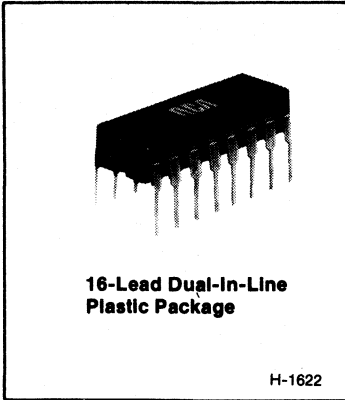


Fig. 7 — Schematic diagram of CA3221E.



TV Horizontal Oscillator

For Color and Monochrome Receivers

Features:

- Sync separator
- Noise gate input
- Internal precision timing ramp
- Dual-time-constant phase-locked loop
- Output suitable for transistor or thyristor deflection systems
- Reduced power dissipation

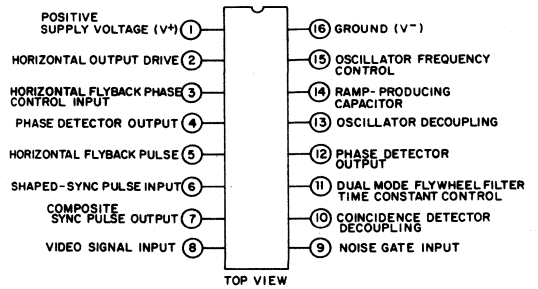
The RCA-CA920AE is a silicon monolithic integrated circuit intended for use in the horizontal stages of color and monochrome television receivers. This device performs the functions of a sync separator, noise gate, and horizontal oscillator with dual-time-constant switching in the fly-wheel loop. It also generates automatic phase control between horizontal flyback pulses and the horizontal oscillator frequency and provides fast edge switching drive for transistor or thyristor horizontal output stages.

The CA920AE is compatible with the industry type TBA920 in both lead arrangement and electrical operation, although the CA920AE features reduced operating current.

The CA920AE is supplied in the 16-lead dual-in-line plastic package.

•Formerly Dev. Type No. TA6773.

TERMINAL ASSIGNMENT



92CS-27479

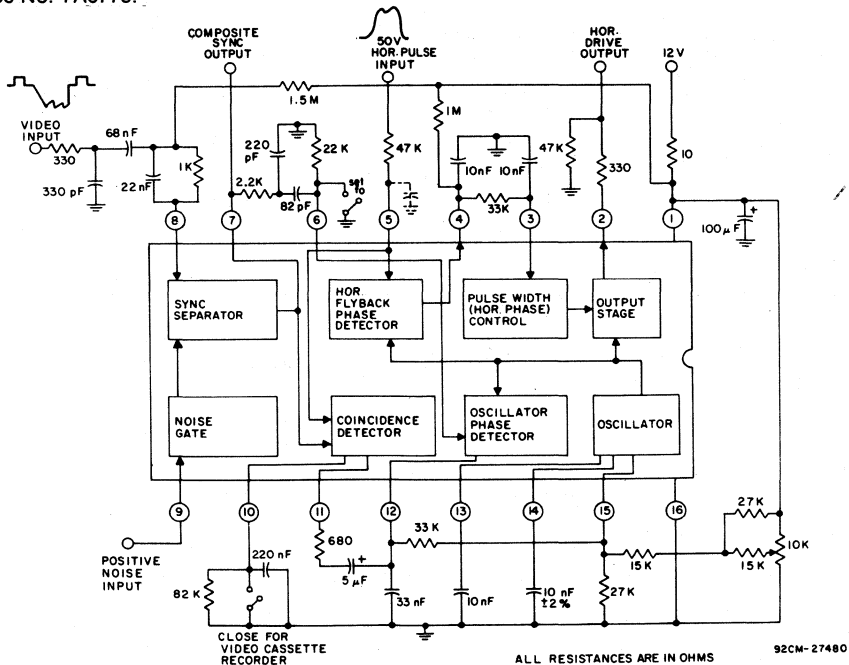


Fig. 1 - Functional block diagram of the CA920E with typical peripheral circuitry.

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CA920AE

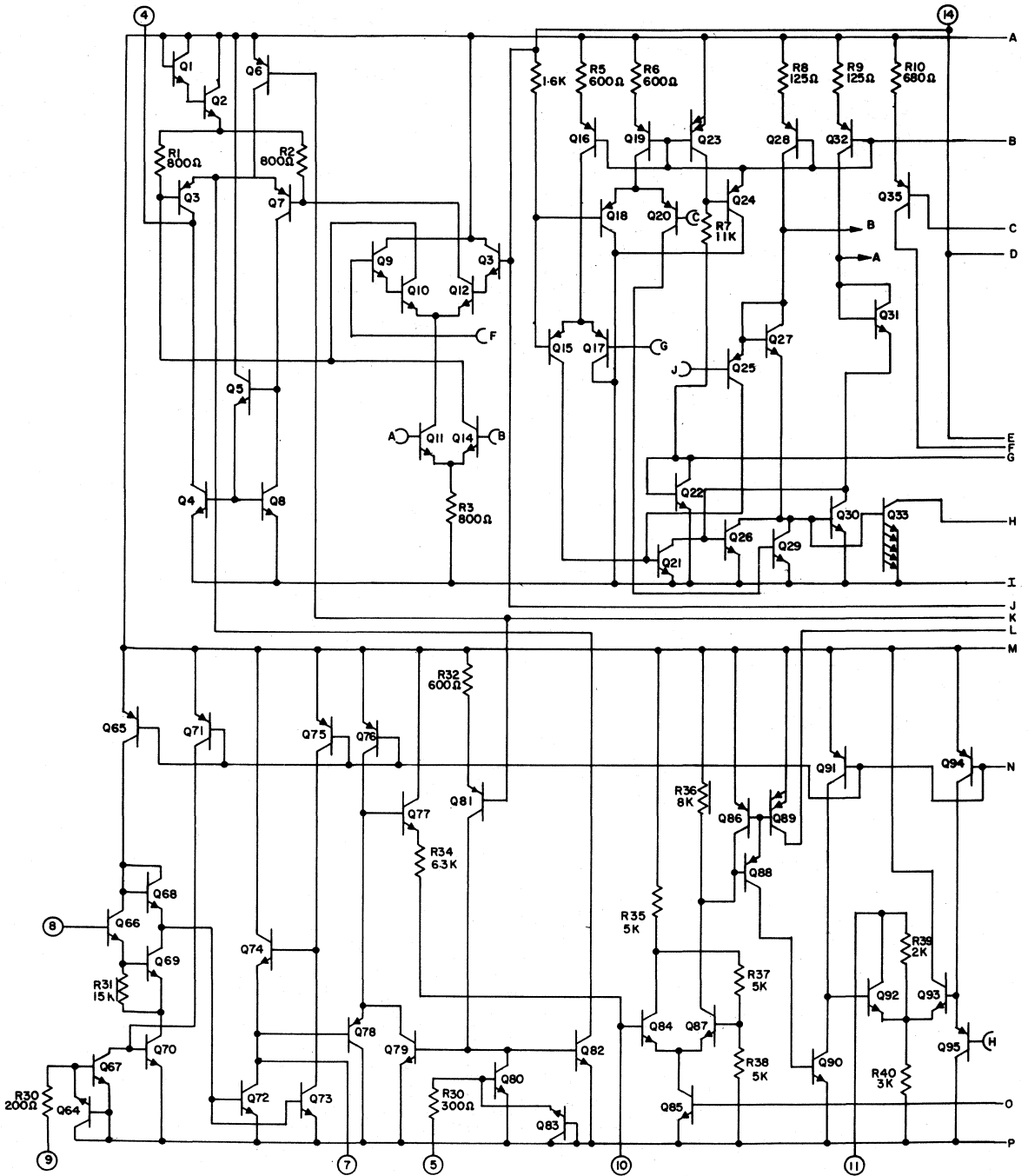
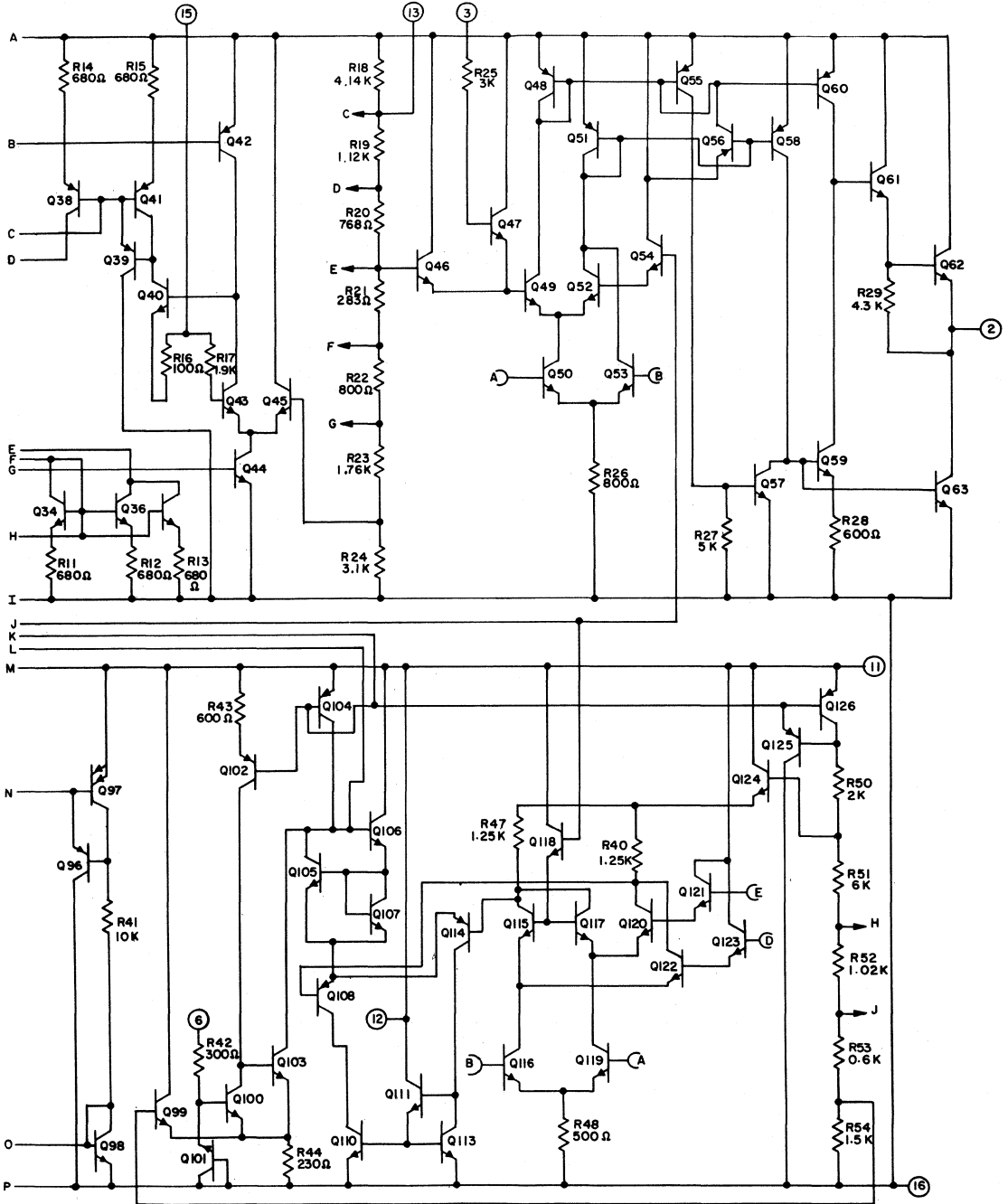


Fig. 2 - Schematic diagram of the CA920AE (cont'd on next page).

TV/CATV Circuits
CA920AE



92CL-31005

Fig. 2 - Schematic diagram of the CA920AE (cont'd from previous page).

Linear Integrated Circuits

CA920AE

MAXIMUM RATINGS, Absolute Maximum Values:

DC SUPPLY VOLTAGE	13.2 V
DEVICE DISSIPATION:	
Up to $T_A = 55^\circ\text{C}$	750 mW
Above $T_A = 55^\circ\text{C}$	Derate linearly at 7.9 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:	
Operating	-40 to $+85^\circ\text{C}$
Storage	-65 to $+150^\circ\text{C}$
LEAD TEMPERATURE (During soldering):	
At a distance not less than 1/32" (0.79 mm) from case for 10 seconds max.	$+265^\circ\text{C}$

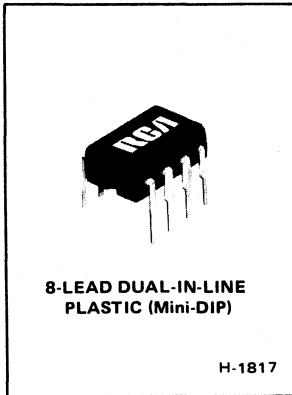
ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, and Supply Voltage (V^+) = 12 V, Unless otherwise specified. See Fig. 1.

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
Supply Current, Term. 1, I^+	Term. 2 open		22		mA
Video Characteristics (Term.8):					
Input Voltage V_8	Peak to peak	1.5	3	6	V
Input Current I_8	Peak			10	mA
Noise Gate Characteristics (Term.9):					
Input Current I_9		0.03		10	mA
Reverse Input Current I_9				-10	mA
Horizontal Flyback Positive Pulse Characteristics (Term.5):					
Input Voltage V_5		1		3	V
Input Current I_5		0.05	1	10	mA
Input Impedance Z_5			0.4		k Ω
Positive Sync Characteristics (Term.7):					
Output Voltage V_7	Peak to peak		10		V
Output Impedance Z_7	Leading edge		50		Ω
Output Impedance Z_7	Trailing edge		100		Ω
Horizontal Output Characteristics (Term.2):					
Output Current $I_2\text{MAX}$	Peak			200	mA
Output Current $I_2\text{AV}$	Average			20	mA
Output Pulse Width t_W		12		32	μs
Output Impedance Z_2	Leading edge		2.5		Ω
Output Impedance Z_2	Trailing edge		15		Ω
Horizontal Oscillator Characteristics (Term.15):					
Free-Running Frequency f_o	No sync input	14.84	15.625	16.41	kHz
Free-Running Frequency f_o	$V^+ = 4.5\text{ V}$	14.06	(Note 1)	17.19	kHz
Oscillator Cut-out Voltage	V^+ varied		4.0		V
Oscillator Pull-in Range			± 1.0		kHz
Phase Control (Note 2)				15	μs

Note 1: Free-running frequency at 12 V adjusted to 15.625 kHz.

Note 2: External delay between the leading edge of output pulse at Term. 3 and the start of the horizontal flyback pulse.

TV Horizontal Processors



CA1391E — Positive Horizontal Sawtooth Input
CA1394E — Negative Horizontal Sawtooth Input

Features:

- Internal shunt regulator
- Linear balanced phase detector
- Preset hold control capability
- ± 300 -Hz pull-in (typ.)
- Low thermal frequency drift
- Small static phase error
- Variable output duty cycle
- Adjustable dc loop gain

The RCA-CA1391E and CA1394E are monolithic integrated circuits designed for use in the low-level horizontal section of monochrome or color television receivers. Functions include a phase detector, an oscillator, a regulator, and a pre-driver.

The CA1391E and CA1394E are electrically equivalent and pin compatible with industry types 1391 and 1394 in similar packages.

These types are supplied in an 8-lead dual-in-line plastic (Mini-DIP) package, and operate over an ambient temperature range of 0 to +85°C.

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

DC SUPPLY CURRENT	40 mA
DC OUTPUT VOLTAGE	40 V
DC OUTPUT CURRENT	30 mA
SYNC INPUT VOLTAGE	5 V _{p-p}
SAWTOOTH INPUT VOLTAGE	5 V _{p-p}
DEVICE DISSIPATION:	
Up to $T_A = 25^\circ\text{C}$	625 mW
Above $T_A = 25^\circ\text{C}$ derate linearly	5 mW/°C
AMBIENT TEMPERATURE RANGE:	
Operating	0 to +85°C
Storage	-65 to +150°C
LEAD TEMPERATURE (During Soldering):	
At distance $1/16 \pm 1/32$ in. (1.59 \pm 0.79 mm) from case for 10 seconds max.	+260°C
THERMAL RESISTANCE	200°C/W

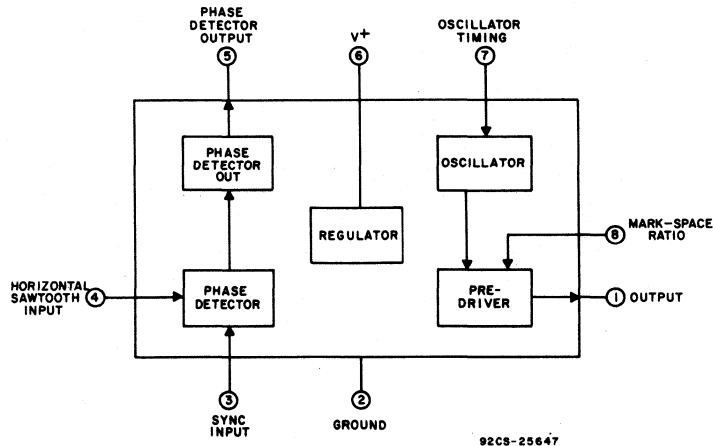


Fig. 1 — Functional block diagram of the CA1391E, CA1394E.

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CA1391E, CA1394E

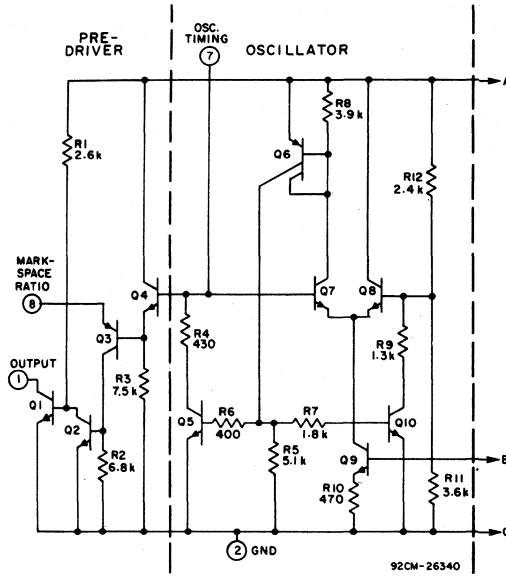


Fig.2 - Schematic diagram of CA1391E, CA1394E.

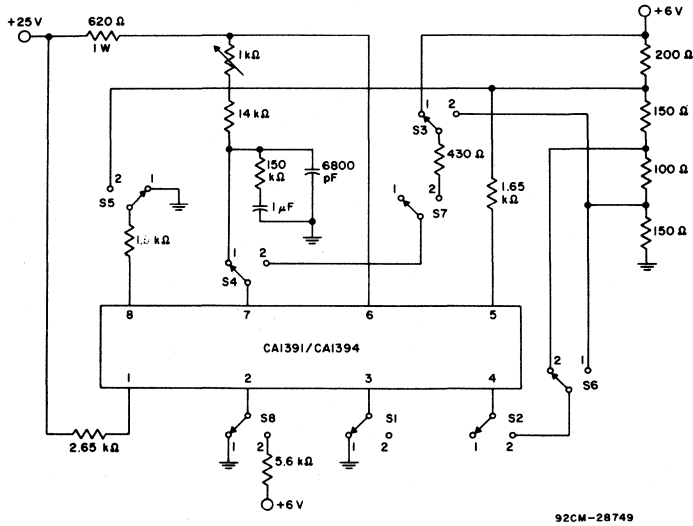


Fig.3 - DC test circuit.

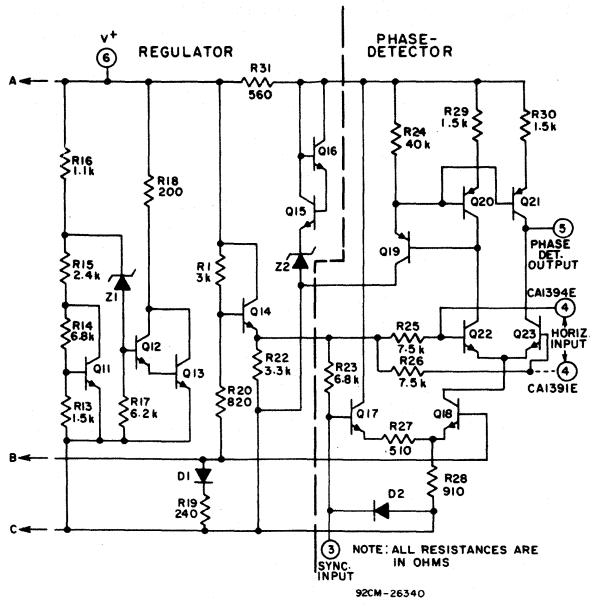


Fig.2 - Schematic diagram of CA1391E, CA1394E (Cont'd).

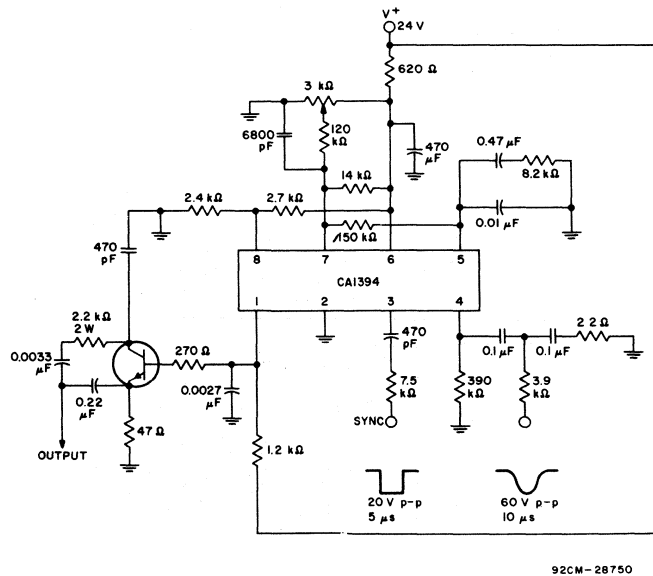


Fig.4 - Typical circuit application.

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CA1391E, CA1394E

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$ (See Fig.3)

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
Supply Voltage	S1, S5, S6 = 2 S2, S3, S4, S7, S8 = 1 Measure term. 6 to Gnd	8	—	9	V
Free-Running Frequency	S1, S5, S6 = 2 S2, S3, S4, S7, S8 = 1 Counter to term. 1	14734	—	16734	Hz
Output Leakage	S2, S3, S6, S8 = 1 S1, S4, S5, S7 = 2 Measure term. 1 to 25 V	—	10	—	mV
Output Saturation	S2, S3, S5, S6, S8 = 1 S1, S4, S7 = 2 Measure term. 1 to Gnd	—	60	—	mV
Phase Detector Bias	S2, S5, S6, S8 = 1 S1, S3, S4, S7 = 2 Measure term. 3 to Gnd	—	1.9	—	V
Phase Detector Leak	S5, S8 = 1 S1, S2, S3, S4, S6, S7 = 2 Measure term. 5 to +4 V	-2	—	+2	mV
Phase Detector Low	S1, S5, S8 = 1 S2, S3, S4, S6, S7 = 2 Measure term. 5 to +4 V	-0.55*	—	—	V
Phase Detector High	S1, S5, S6, S8 = 1 S2, S3, S4, S7 = 2 Measure term. 5 to +4 V	+0.55*	—	—	V
Phase Detector Balance	$V_{DET2} + V_{DET3}$	-100	—	+100	mV
Sync Diode	S1, S2, S3, S4, S6, S7 = 1 S5, S8 = 2	0.3	—	1.2	V
Static Phase Error	See Fig.4	—	0.5	—	μs
Oscillator Pull-in Range		—	± 300	—	Hz
Oscillator Hold-in Range		—	± 900	—	Hz

* Polarity reversed in the CA1391.

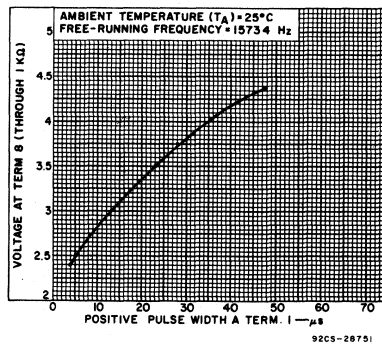


Fig.5 — Duty cycle at the pre-drive output (term.1) as it is affected by the input at term. 8.

CIRCUIT OPERATION

(See schematic diagram, Fig.2)

The CA1391 and CA1394 contain the oscillator, phase detector, and predriver sections necessary for the television horizontal oscillator and AFC loop.

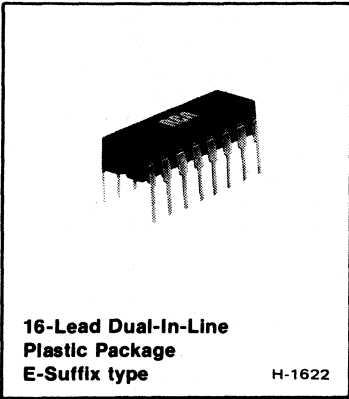
The oscillator is an RC type with terminal 7 used to control the timing. If it is assumed that Q7 is initially off, then an external capacitor connected from terminal 7 to ground charges through an external resistance connected between terminals 6 and 7. As soon as the voltage at terminal 7 exceeds the potential set at the base of Q8 by resistors R11 and R12, Q7 turns on, and Q6 supplies base current to Q5 and Q10. Transistor Q5 discharges the capacitor through R4 until the base bias of Q7 falls below that of Q8, at which time, Q7 turns off, and the cycle repeats.

The sawtooth generated at the base of Q4 appears across R3 and turn off Q3 whenever the sawtooth voltage rises to a value that exceeds the bias set at terminal 8. By adjusting the potential at terminal 8, the duty cycle at the pre-drive output (terminal 1) may be changed.

The phase detector is isolated from the remainder of the circuit by R31, Z2, Q15 and Q16. The phase detector consists of the comparator Q22 and Q23, and the gated current source Q18. Negative-going sync pulses at terminal 3 turn off Q17, and the current division between Q22 and Q23 is then determined by the phase relationship of the sync and the sawtooth waveform at terminal 4, which is derived from the horizontal flyback pulse. If there is no phase difference between the sync and sawtooth, equal currents flow in the collectors of Q22 and Q23 during each half of the sync pulse period. The current in Q22 is turned around by current mirror Q20 and Q21 so that there is no net output current at terminal 5 for balanced conditions. When a phase offset occurs, current flows either in or out of terminal 5. In circuit applications, this terminal is connected to terminal 7 through an external low-pass filter, thereby controlling the oscillator.

Shunt regulation for the circuit is obtained by using a V_{BE} and zener multiplier. Resistors R13 and R14 multiply the V_{BE} of Q11, and the ratio of R15 and R16 multiplies the voltage of the zener diode Z1.

CA3154E



TV Sync/AGC/Horizontal Signal Processor

FEATURES:

- Horizontal oscillator with AFC
- Sync separator with noise immunity
- Strobed AGC system
- IF AGC output
- Delayed outputs for forward or reverse AGC tuners
- Internal noise threshold

The RCA-CA3154E is a monolithic integrated circuit TV signal processor designed for use in color or monochrome receivers. Circuit functions include a horizontal oscillator with AFC, a sync separator, and a key AGC system. The AGC system provides output signals for IF (reverse) and tuner (forward and/or reverse). The wide frequency-range horizontal oscillator has high stability at 503.3 kHz. When the CA3154E is used in conjunction with the CA3157E horizontal/vertical countdown circuit, the need for horizontal and vertical hold controls is eliminated.

- High-impedance video input
- Choice of dual external time constants for sync separator noise immunity
- RF AGC delay externally controlled
- Output short-circuit protection

The CA3154E is supplied in a 16-lead dual-in-line plastic package.

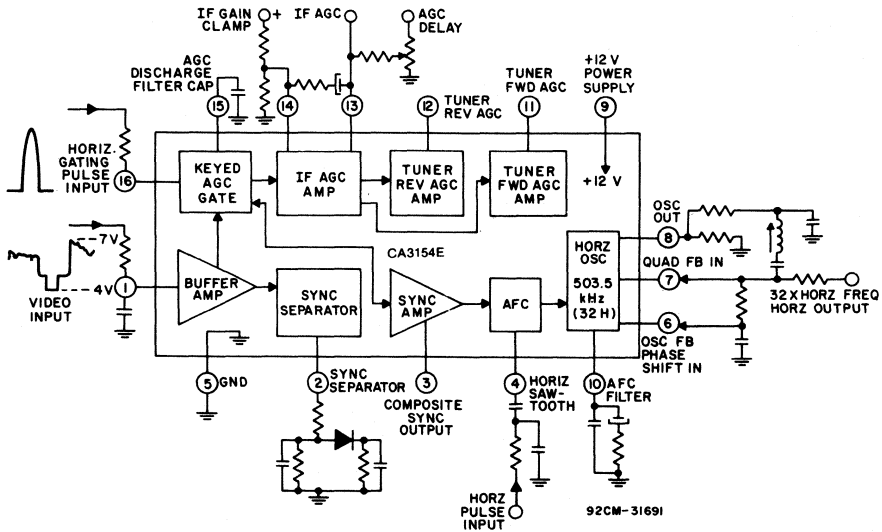


Fig. 1 — Functional block diagram of CA3154E.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE	15 V
DEVICE DISSIPATION:	
Up to $T_A = 55^\circ\text{C}$	750 mW
Above $T_A = 55^\circ\text{C}$	derate linearly 7.9 mW/ $^\circ\text{C}$
AMBIENT-TEMPERATURE RANGE:	
Operating	-40 to $+85^\circ\text{C}$
Storage	-65 to $+150^\circ\text{C}$
LEAD TEMPERATURE (During soldering):	
At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10 s max.	$+265^\circ\text{C}$

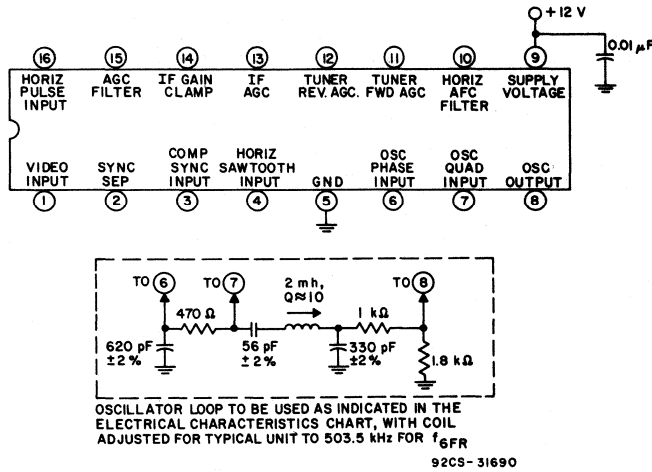


Fig. 2 — Electrical characteristics test circuit.

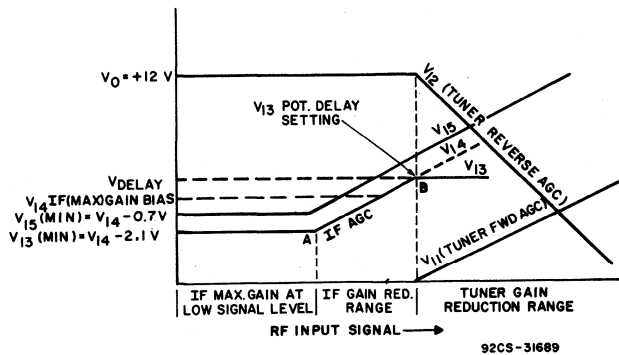


Fig. 3 — Typical operation of AGC circuits using the CA3154E.

Linear Integrated Circuits

CA3154E

ELECTRICAL CHARACTERISTICS, at $T_A = 25^\circ\text{C}$, terminal 5 to Gnd, and terminal 9 to +12 V unless otherwise specified.

CHARACTERISTIC	TEST CONDITIONS Terminals Connected As Shown Below	LIMITS			UNITS
		Min.	Typ.	Max.	
Power Supply Current, I_g	Measure (9)	10	—	22	mA
Video Inverter Voltage, V_2	(1) to +14V, (2) 12 k Ω to Gnd, (3) 27 k Ω to Gnd, Measure (2)	5.2	—	6.4	V
Sync Separator High Output Voltage, V_{3H}	Same as above	10.7	—	—	V
Sync Separator Low Output Voltage, V_{3L}	(1) to +4V, (3) 27 k Ω to Gnd, Measure (3)	—	—	1.3	V
Video Noise Clamp Voltage, V_3 Clamp	(1) to +3.1V, (3) 27 k Ω to Gnd, Measure (3)	10.7	—	—	V
AGC Discharge Current, I_{15} Discharge	(1) to +4.4V, (2) 10 k Ω to Gnd, (15) 470 Ω to +6V, (16) 27 k Ω to 12V, Measure (15)	0.6	—	1.4	mA
AGC Charge Current, I_{15} Charge	(1) to +3.45V, otherwise same as above	-2.1	—	-4.8	mA
AGC Comparator Leakage, I_{15} Leakage	(1) to +3.45V, (2) 10 k Ω to Gnd, (15) 4.7 k Ω to +6V, Measure (15)	-20	—	+20	μA
AGC Threshold Voltage, V_{1TH}	Adj. (1) for $I_{15} = 0 \pm 0.1$ mA, (2) 10 k Ω to Gnd, (15) 4.7 k Ω to +6V, (16) 27 k Ω to +12V, Measure (1)	3.8	4	4.3	V
Minimum IF AGC, V_{13L}	(11) 10 k Ω to Gnd, (12) 10 k Ω to +12V, (13) 22 k Ω to +5V, (14) 1 k Ω to +2.95V, (16) 1 k Ω to +2.2V, Measure (13)	0.75	—	1.25	V
Forward Tuner AGC Leakage Current, I_{11} Leakage	(11) 10 k Ω to Gnd, (12) 10 k Ω to 12V, (13) 2.2 k Ω to +5V, (14) 1 k Ω to +2.95V, (15) 1k Ω to +5.3V, Measure (11)	-20	—	+20	μA
Reverse Tuner AGC Leakage, I_{12} Leakage	Same as above, but Measure (12)	-10	—	+10	μA
IF AGC High Voltage, V_{13H}	Same as above, but Measure (13)	3.65	—	4.15	V
Forward Tuner AGC Low Voltage, V_{11L}	(11) 3.6 k Ω to Gnd, (12) 3.16 k Ω to +12V, (13) 2.2 k Ω to +5V, (14) 1 k Ω to +2.95V, (15) 1 k Ω to +7.9V, Measure (11)	0.8	—	3.2	V
Reverse Tuner AGC Low Voltage, V_{12L}	Same as above, but Measure (12)	1.65	—	3.25	V
Maximum IF AGC Voltage, V_{13H}	(11) 10 k Ω to Gnd, (12) 10 k Ω to +12V, (13) 2.2 k Ω to +5V, (14) 1 k Ω to +2.95V, (15) 1 k Ω to +7.9V, Measure (13)	4.85	—	5.2	V

(continued)

ELECTRICAL CHARACTERISTICS, at $T_A = 25^\circ C$, terminal 5 to Gnd, and terminal 9 to +12 V unless otherwise specified.

CHARACTERISTIC	TEST CONDITIONS Terminals Connected As Shown Below	LIMITS			UNITS
		Min.	Typ.	Max.	
Phase Detector Leakage Current, I_{jOL}	(2) 10 k Ω to Gnd, (3) to Gnd, (4) 5 k Ω to +3.8V, (10) 10 k Ω to +6V, Limit Gnd at (3) to 10 sec., Measure 10	-5	-	+5	μA
Phase Detector Bias Voltage, V_4		2.65	-	3.1	V
Oscillator Output Voltage, V_6	Connect osc-loop shown in test circuit to (6),(7),(8); (3) to Gnd for 10 sec. max., Measure (6)	0.6	-	1.6	V _{p-p}
Oscillator Free-Running Frequency f_{6FR}	Same as above	475	-	535	kHz
Oscillator Frequency High, f_{6H}	Connect osc-CKT shown in test CKT to (10),(7),(8); (2) 10 k Ω to Gnd, (4) 5 k Ω to +18V, Measure (6)	520	-	-	kHz
Oscillator Frequency Low, f_{6L}	Same as above except (4) 5 k Ω to +3.8 V	-	-	485	kHz
Sync Separator Short Circuit, I_3 Max.	(3) 10 Ω to Gnd 10 sec. max.	-	-	40	mA
Oscillator Output Short Circuit, I_8 Max.	(8) 10 Ω to Gnd for 10 sec. max. (3) 10 Ω to Gnd for 10 sec. max.	-	-	130	mA

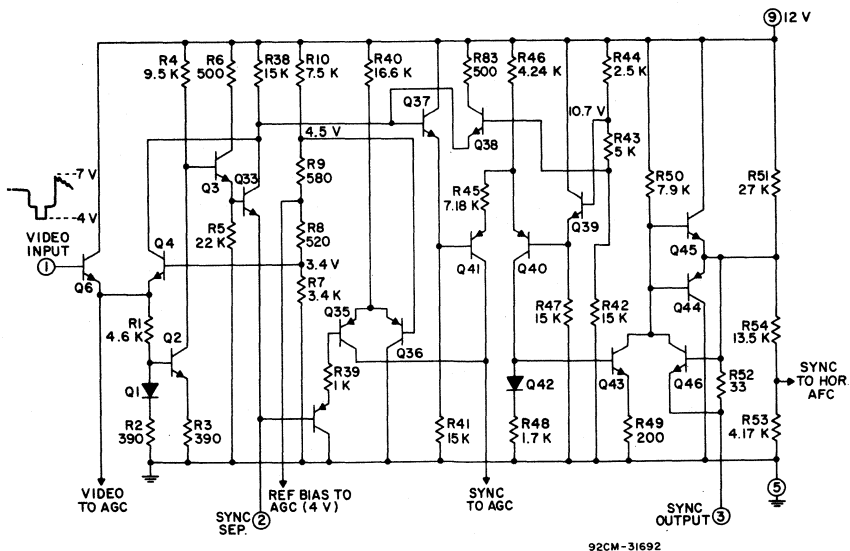


Fig. 4(a) — Schematic of sync separator section of the CA3154E.

Linear Integrated Circuits

CA3154E

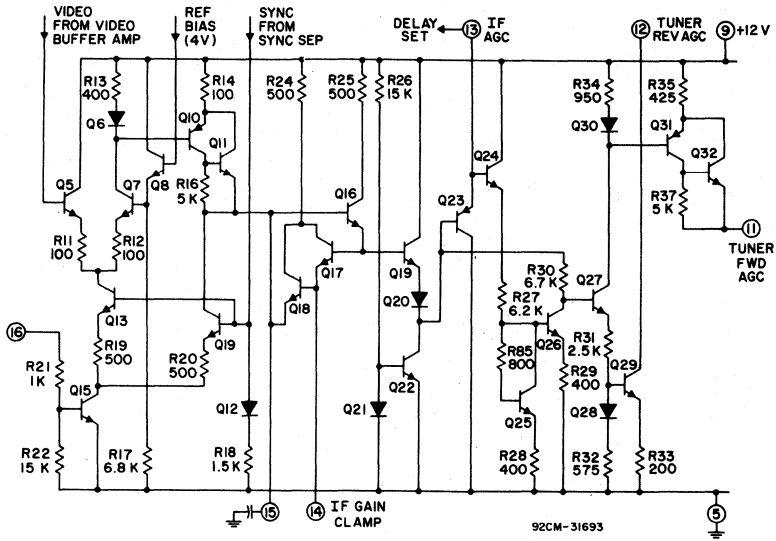


Fig. 4(b) — Schematic of AGC section of the CA3154E.

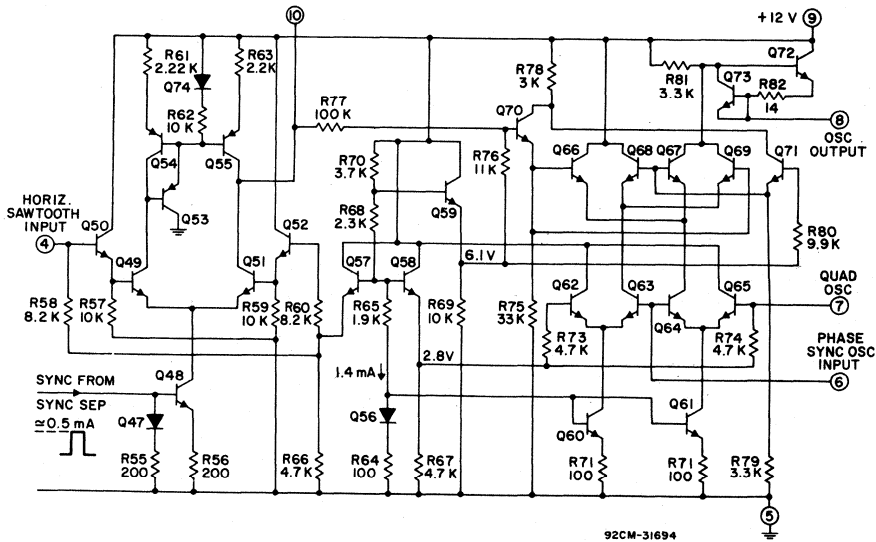


Fig. 4(c) — Schematic of AFC-oscillator section of the CA3154E.

TV/CATV Circuits CA3154E

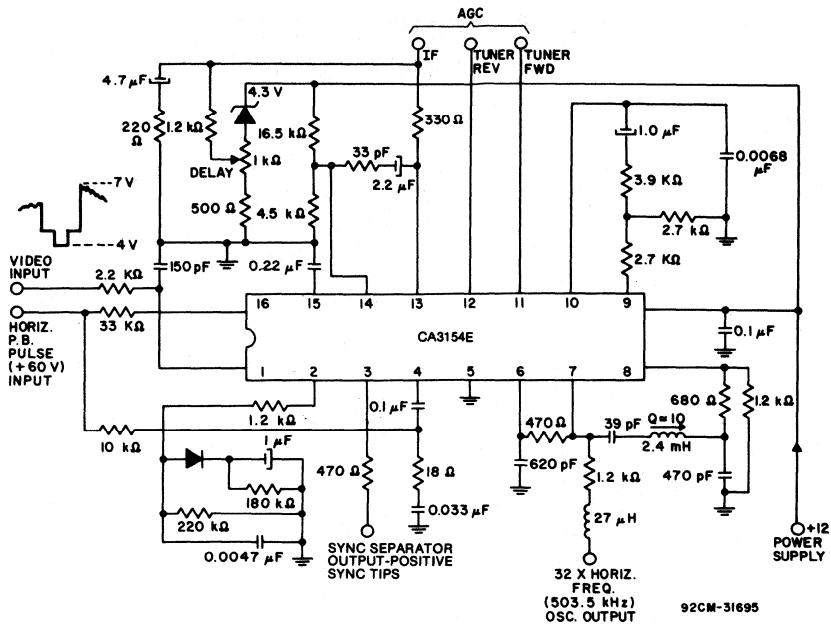
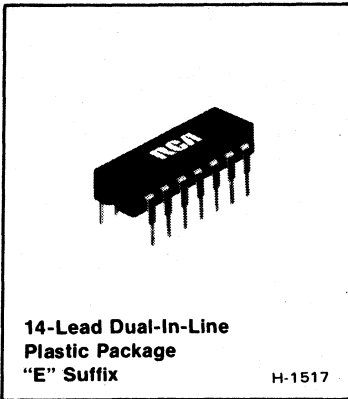


Fig. 5 — Typical application of the CA3154E.

CA3157E



14-Lead Dual-In-Line Plastic Package "E" Suffix

H-1517

TV Horizontal/Vertical Countdown Digital Sync System

FEATURES:

- *Dual-Mode Operations:*
Standard NTSC signals
Non-standard signals (video games, video tape, etc.)
- Automatic mode recognition
- Clock input
- Vertical ramp (sawtooth) generator
- Vertical amplifier
- Vertical blanking generator
- Horizontal drive pulse output
- Ratio-voltage regulator

The RCA-CA3157E is a monolithic I²L integrated circuit TV digital sync system designed for use in consumer applications. It features dual-mode operation and accepts either standard NTSC signals or non-standard signals. An automatic mode-recognition system forces the CA-3157E into the standard mode for NTSC signals or into the non-synchronous mode for non-standard sync signals. Other on-chip functional blocks include a vertical-ramp (sawtooth) generator, a vertical amplifier, a ratio-voltage regulator, and a countdown and phasing circuit that eliminates the need for an external vertical-hold control.

- Excellent noise immunity
- Inherent interlace for NTSC signals
- Vertical-hold control eliminated
- Supply-voltage range = 8.6 to 14.2 V
- Rapid pull-in
- Cochannel sync lockout for NTSC signals
- I²L logic

The CA3157E is supplied in the 14-lead dual-in-line plastic package.

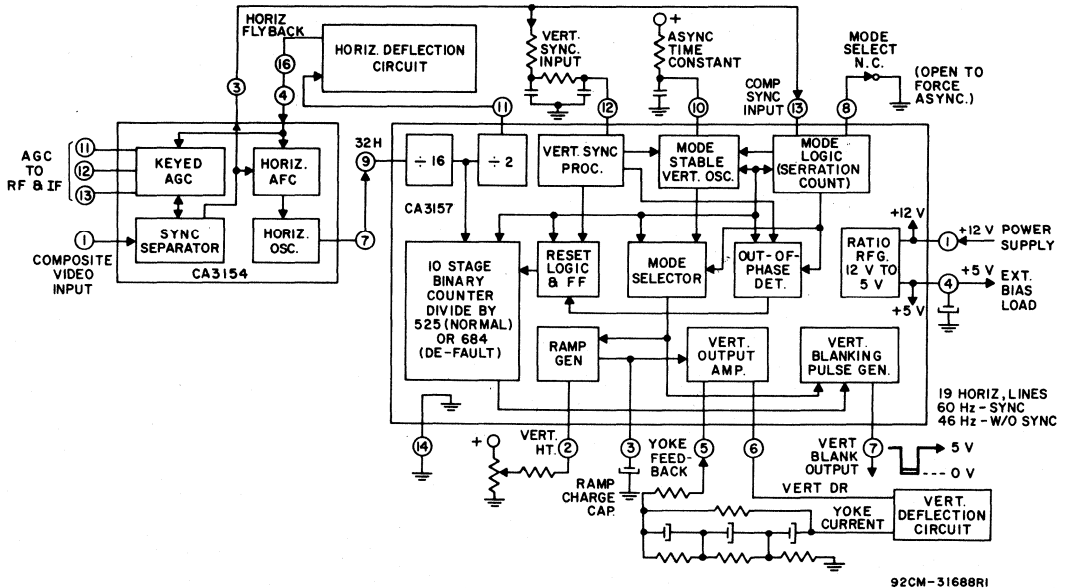


Fig. 1 — Functional block diagram of the CA3157E horizontal/vertical countdown integrated circuit.

(continued from page 1)

and a countdown and phasing circuit that eliminates the need for an external vertical-hold control.

The CA3157E is supplied in the 14-lead in-line plastic package.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE	15	V
DEVICE DISSIPATION:		
Up to $T_A = 70^\circ\text{C}$	530	mW
Above $T_A = 70^\circ\text{C}$	derate linearly at 6.7	mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:		
Operating	0 to 70	$^\circ\text{C}$
Storage	-55 to +150	$^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):		
At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10 seconds max.	+265	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, all switches open unless otherwise specified. See Fig. 2, Test Points 2 and 14 = Gnd

CHARACTERISTIC	TEST CONDITIONS	LIMITS		UNITS
		Min.	Max.	
Amplifier Gain, V6	S2,S5,S6 Closed, Note 1, Test pt. 1 = 12V, 16 = 1V _{RMS} at 1 kHz	0.178	3.16	V _{RMS}
Horizontal Frequency Divider Ratio, $f_9 \div f_{11}$	S3,S7,S8 Closed, Note 7, Test pt. 1 = 14.4V,	32	32	RATIO
Horizontal Pulse Width, Term. II	S3,S7,S8 Closed, Notes 9,10, Test pt. 1 = 8.4V	30	37	μs
	S3,S7,S8 Closed, Notes 9,10,11, Test pt. 1 = 14.4V	30	36	
Asynchronous Non-Coincident Frequency Divide Ratio, $f_9 \div f_3$	S3,S7,S8 Closed, Notes 9,12,13, 14,15, Test pt. 1 = 14.4V, 8 = 0.2V, 12 = 1.5V	10944	10944	RATIO
Ramp Charge Pulse Width, Term. 3	S3,S7,S8 Closed, Notes 13,15, Test pt. 1 = 14.4V, 8 = 0.2V, 12 = 1.5V	185	315	μs
Asynchronous Coincident Noise Immunity, Hold-Off Freq. Divider Ratio, $f_8 \div f_3$	Notes 9,12,13,15,16,17, Test pt. 1 = 14.4V, 8 = 0.2V	7872	7872	RATIO
Synchronous Divider Ratio, $f_9 \div f_3$	S3,S7,S8 Closed, Notes 9,13,15, 18,19, Test pt. 1 = 14.4V, 8 = 0.2V, 12 = 1.5V	8400	8400	RATIO
Ramp Charge Pulse Width, Term. 3	S3,S7,S8 Closed, Notes 9,10,13, 15,18,20, Test pt. 1 = 14.4V, 8 = 0.2V, 12 = 1.5V	192	192	CLOCKS
Vertical Blanking Pulse Width, Term. 7	S3,S7,S8 Closed, Notes 9,10,13, 15,18,21, Test pt. 1 = 14.4V, 8 = 0.2, 12 = 1.5V	608	608	CLOCKS

Linear Integrated Circuits

CA3157E

(continued from page 2)

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, all switches open unless otherwise specified.

See Fig. 2, Test Points 2 and 14 = Gnd

CHARACTERISTIC	TEST CONDITIONS	LIMITS		UNITS
		Min.	Max.	
Mode Recognition Field Count, Freq. Divider Ratio, $f_g \div f_3$	S3,S7,S8 Closed, Notes 9,13, 14,15,18,22, Test pt. 1 = 14.4V, 8 = 0.2V, 12 = 1.5V			RATIO
	Initial Fields 9 Serrations	8400	8400	
	First Field, 8 Ser.	8400	8400	
	Second Field, 8 Ser.	8400	8400	
	Third Field, 8 Ser.	8400	8400	
	Fourth Field, 8 Ser.	8400	8400	
	Fifth Field, 8 Ser.	8400	8400	
	Sixth Field, 8 Ser.	8400	8400	
	Seventh Field, 8 Ser.	10944	10944	
Eighth Field, 9 Ser.	8400	8400		
Confidence of Coincidence Field Count, Freq. Divider Ratio, $f_g \div f_3$	S3,S7,S8 Closed, Notes 9,13, 15,18,23, Test pt. 1 = 14.4V 8 = 0.2V			RATIO
	First Field	4200	4200	
	Second Field	8400	8400	
	Third Field	8400	8400	
	Fourth Field	8400	8400	
	Fifth Field	8400	8400	
	Sixth Field	8400	8400	
	Seventh Field	8400	8400	
	Eighth Field	8400	8400	
Ninth Field	4200	4200		

Notes:

1. Stop clock when terminal 7 is high
2. Stop clock when terminal 9 is low
3. Stop clock when terminal 9 is high
4. Stop clock when terminal 7 is low
5. Stop clock when terminal 11 is high
6. Stop clock when terminal 11 is low
7. Clock frequency = 600 kHz; clock amplitude: low $\leq 0.45\text{ V}$, high $\geq 0.95\text{ V}$ (5 V max.)
8. Frequency at terminal 9 (clock) divided by frequency at terminal 11 (hor. out)
9. Clock frequency = 500 kHz, clock amplitude same as in note 7
10. Pulse width measured at 2 V point on output waveform
11. Total capacity = 50 pF when measuring pulse width
12. Sync serrations = 8 (See Fig. 4)
13. Sync amplitude: low state $\leq 1.2\text{ V}$; high state $\geq 4\text{ V}$ (6 V max. with positive sync tips)
14. Frequency at terminal 9 (clock) divided by frequency at terminal 3 (ramp control)
15. Initialize or repeat initialization procedure before doing this test (See Fig. 2)
16. Apply a pulse 1 clock wide, 7808 clocks after first positive transition at terminal 3 (See Fig. 5)
17. Default count determined by $684 \times 16(\text{H}) = 10944$
18. Sync serrations = 9
19. Hold-off count determined by $492 \times 16(\text{H}) = 7872$
20. Number of clocks occurring within ramp gate period (See Fig. 6)
21. Number of clocks occurring during the blanking gate period (See Fig. 7)
22. This series of tests checks the mode recognition circuit. The first test after initialization applies 9 serrations at the sync input terminal. The IC should go to the synchronous count ratio of 8400. During the next seven fields only 8 serrations are applied. The CA3157 should maintain the synchronous count ratio of 8400 for the first six fields. At the seventh field the CA3157 should go to default count of 10944. The test concludes with a 9 serration input. The CA3157 should revert to a synchronous count of 8400 (See Fig. 8)
23. This test checks the operation of the out-of-sync detector by applying out-of-phase sync pulses to terminal 12. The CA3157 will count eight fields before resetting to the sync pulse (See Fig. 9)

STATIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V^+ = 12\text{ V}$, Switches open unless otherwise specified. See Fig. 2. Test Points 2,8,12, and 14 grounded unless otherwise specified

CHARACTERISTIC	TEST CONDITIONS	CONNECT TEST POINTS AS SHOWN BELOW								LIMITS		UNITS	
		TEST POINT NOS.								Min.	Max.		
		1	3	4	5	6	10	11	13				
Ratio Regulator Voltage, V_4 : Load	S2 Closed, Note 1	12V		-20 mA	2V						4.9	5.5	V
		14.4V			2V						5.8	6.8	
Vertical Blanking Output, V_7 : Unblanked	S2 Closed, Notes 1,4	12V		-20 mA	G						2.5	5	V
		12V			G						0.09	0.5	
Horizontal Output Voltage, V_{11} : High	Test pt. 15=8V, S2 Closed, Notes 5,6	14.4			G						7	8.1	V
		12V			G			20 mA			0.09	0.32	
Vertical Output Voltage, V_6 : Off	S4 Closed, Note 1	12V			G	1 mA					0.6	1.4	V
		12V	G			-20 mA					3.1	5.1	
Difference Voltage, V_3-V_5	S2 Closed, Note 1	12V			4V	-20 mA					-0.15	0.15	V
Supply Current, I_1	S2 Closed, Note 1	14.4V			2V						10	35	mA
Clock Input Current, I_9 : Clock High	S2 Closed, Note 3	14.4V			2V						65	150	μA
		14.4V			2V						-7	7	
Composite Sync Input Current, I_{13} : Sync High	S2 Closed, Note 3	12V			2V				4V		100	700	μA
		14.4V			2V				0V		-25	25	
Forced Asynchronous Current, I_8	S2 Closed, Note 3, Test pt. 8 = 4.5V	12V			2V						100	700	μA
Ramp Current, I_3	S3 Closed, Note 1, Test pt. 2 = 50 μA	12V	4.5V								45	57	μA
Δ Ramp Current, ΔI_3	S3 Closed, Note 1, Test pt. 2 = 50 μA	12V	1.5V								-3	3	μA
Async Time Constant Current, I_{10} : Charge	S2 Closed, Note 4	12V			2V		3V				10	40	μA
		12V			2V		4.5V				1	5	
Vert. Sync. Input Current, I_{12} : Normal	S2 Closed, Note 4, Test pt. 12 = 2.3V	12V			2V						75	300	μA
		12V			2V						0.1	3	

CA3157E

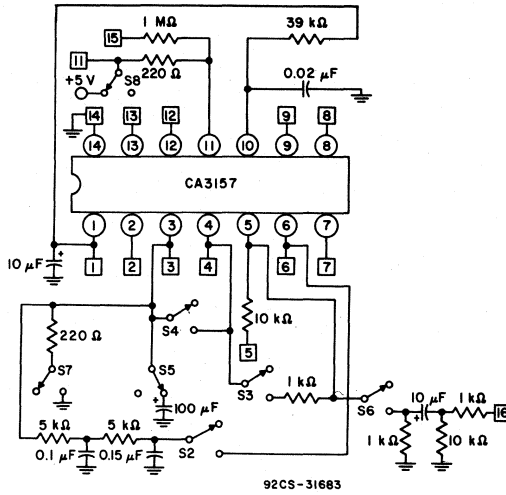
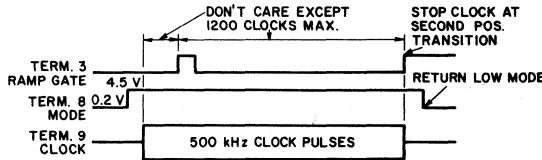


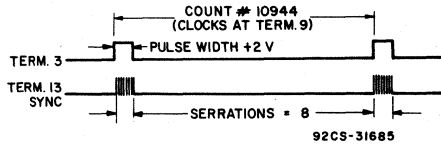
Fig. 2 - Electrical characteristics test circuit.



NOTE: STOP CLOCK AT SECOND POSITIVE TRANSITION OF TERM. 3. RETURN TERM. 8 TO GROUND. THIS CLEARS ALL INTERNAL COUNTERS.

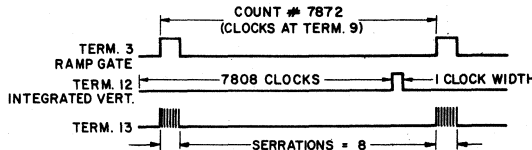
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Fig. 3 - Initialization timing diagram (applies to all tests referenced to Note 15).



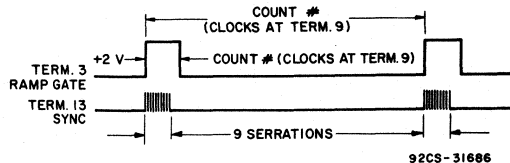
92CS-31685

Fig. 4 - Asynchronous non-coincident divide ratio (applies to all tests referenced to Note 12).



92CS-31684

Fig. 5 - Asynchronous coincident noise immunity hold-off (applies to test referenced to Note 16).



92CS-31686

Fig. 6 - Synchronous non-coincident divider ratio and ramp gate pulse width (applies to test referenced to Note 20).

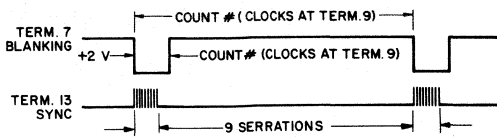


Fig. 7 — Blanking synchronous divider ratio and blanking pulse width (applies to test referenced to Note 21).

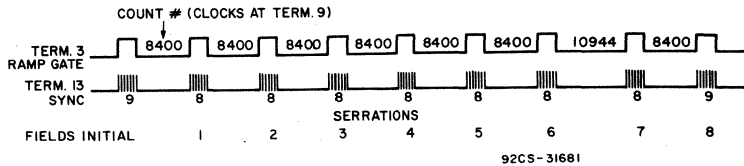


Fig. 8 — Mode recognition field count test (applies to test referenced to Note 22).

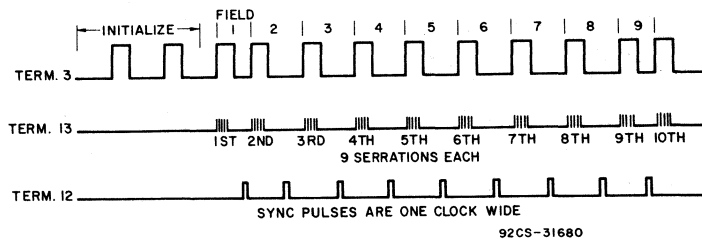


Fig. 9 — Out-of-sync detector test for confidence of coincidence field count at terminal 3 (applies to test referenced to Note 23).

Circuit Operation

Fig. 1 shows the major functional elements of the CA3157E. An external oscillator (CA3154E) supplies an input to terminal 9 of the CA3157E that is 32 times the horizontal rate. An internal divide-by-16 counter converts this input ($32f_H$) to $2f_H$ for use elsewhere in the CA3157E. This $2f_H$ signal is further divided to f_H , which is available at terminal 11 to drive the horizontal deflection circuits. A divide-by-525 counter further divides the $2f_H$ signal to generate the vertical ramp generator timing pulses and the vertical blanking pulse.

A phasing circuit (part of the mode recognition and vertical regeneration circuits) insures that the 525 counter is reset in coincidence with the vertical sync. It does this by comparing the internally generated vertical pulse with an external integrated vertical sync signal applied to terminal 12. The automatic mode recognition circuit forces the CA3157E into the standard mode for NTSC signals or into the non-synchronous mode for non-standard sync signals such as video games. An input control signal

(or no connection) at terminal 8 places the CA3157E into non-synchronous operation.

The vertical retrace signal is converted to a ramp if a capacitor is connected between terminal 3 and ground. The slope of the ramp corresponds to vertical size and is controlled by changing the input current to terminal 2. The ramp is connected to the inverting input of a difference amplifier. The output of this amplifier is connected to terminal 6, and is used to drive the vertical output stage. The non-inverting input of the amplifier is at terminal 5, and a voltage derived from the yoke current may be applied to this terminal for improvement of linearity.

The pulse width of the vertical blanking signal at terminal 7 is 608 clocks wide in the synchronous mode, and is adjustable in width by changing the monostable rc network at terminal 10 for the non-synchronous mode.

The proportional voltage regulator output at terminal 4 is about 43% of the supply voltage at terminal 12. The maximum external load current is 20 mA peak.

CA3159E



Horizontal Processor and AGC Detector

FEATURES:

- AGC voltage
- Separated sync
- 31.5 kHz oscillator
- Gates AGC and sync for noise immunity

The CA3159E is a monolithic integrated circuit designed for use as a horizontal processor and AGC detector in color or black-and-white TV receivers. It performs the functions of AGC, sync separation, and noise immunity, and a 31.5 kHz

oscillator is provided for use with vertical-countdown circuits.

The CA3159E is supplied in a 16-lead dual-in-line plastic package.

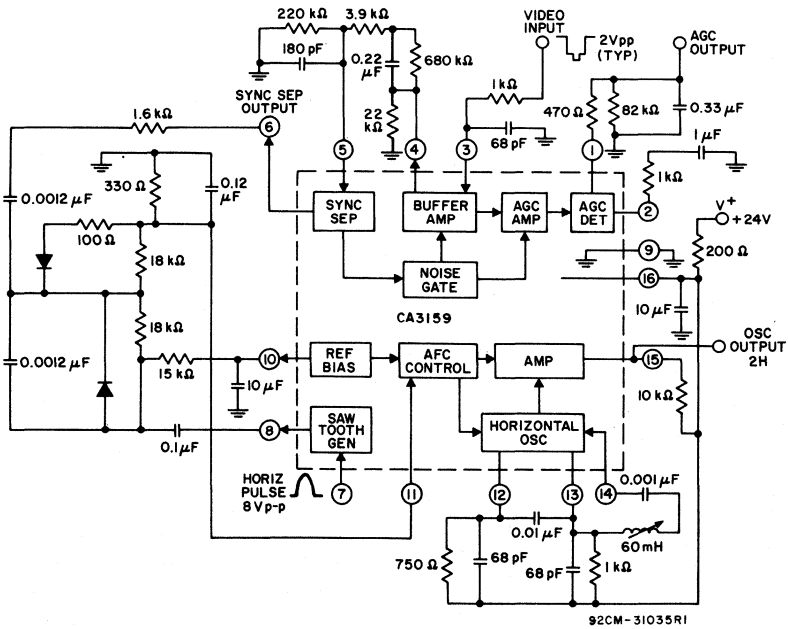


Fig. 1 — Functional block diagram of CA3159E.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE	+30 V
DC SUPPLY CURRENT	30 mA
DEVICE DISSIPATION:		
Up to $T_A = 55^\circ\text{C}$	750 mW
Above $T_A = 55^\circ\text{C}$	Derate linearly at 7.9 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:		
Operating	-40 to +85 $^\circ\text{C}$
Storage	-65 to +150 $^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):		
At distance 1/16 ± 1/32 inch (1.59 ± 0.79 mm)	
from case for 10s max.	+265 $^\circ\text{C}$

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V^+ = 28\text{ V}$, all switches open unless otherwise specified. (See Fig. 2)

CHARACTERISTIC	TEST CONDITIONS	TERM. MEAS.	TYPICAL VALUES	UNITS
AGC Voltage	S1, S9 closed	1	1.85	V
Noise Inverter ¹	S2, S9 closed	1	0.7	V
Shift Threshold ¹	S2, S3 closed	1	20	V
Sync Level	S1, S9 closed	4	18	V
Positive Pulse ²	S5 closed	7	25	V
Positive Sawtooth ³	S5, S6 closed	8	3	V
Sync Low	S3, S4 closed	6	1.5	V
Supply Current		16	20	mA
Free-Running Freq. ⁴	S7, S8, S9 closed	15	31.5	kHz
Duty Cycle	S7, S8, S9 closed	15	48	%

1. A = 3 V, B = 1.2 V, - 1 mA to term. I
2. C = 0.2 mA

3. C = 0.2 mA, D = 5 mA
4. Adjust LI, $V^+ = 20\text{ V}$

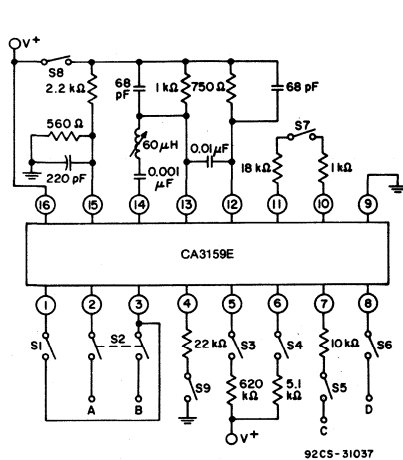
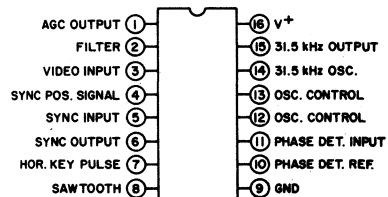


Fig. 2 - DC test circuit.

**CA3159E
TERMINAL ASSIGNMENT**



92CS-31036

CA3159E

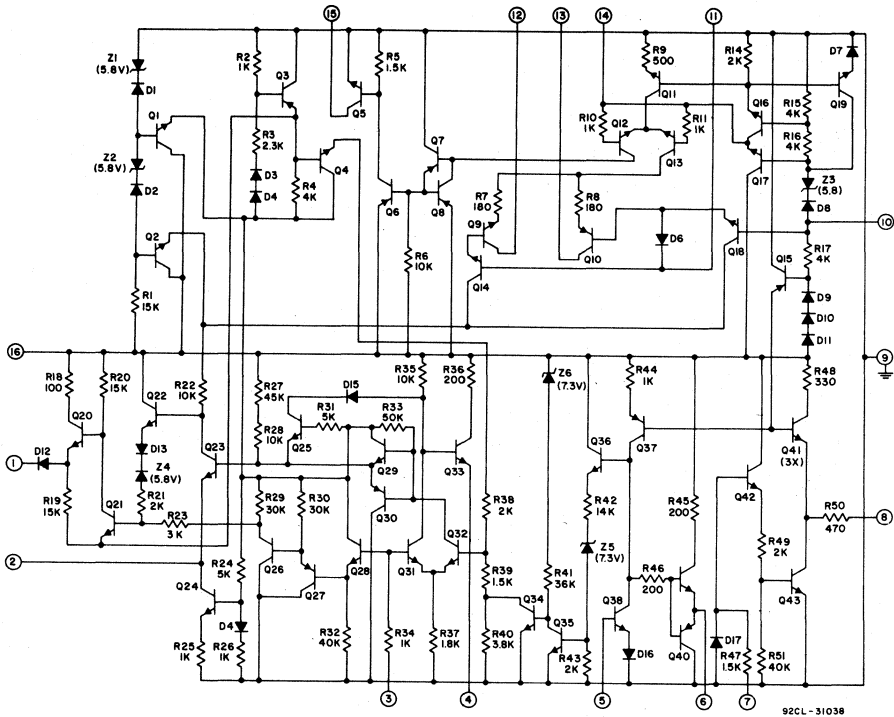


Fig. 3 — Schematic diagram of the CA3159E.

Circuit Description

The negative sync video input at terminal 3 is the detected video if. This video signal is buffered and V_{be} compensated by emitter-followers Q28, Q27, and Q26. The buffered video signal is applied between the base of Q21 and a temperature-stable 2-V reference. Q21 is normally in saturation, and the negative sync pulse imparts a positive swing to the base of Q20. Q20 is used as a peak rectifier driving a capacitor at terminal 1. The voltage at terminal 1 is the AGC control voltage that sets the if gain such that the sync pulses drop to just below the 2 V level, driving Q21 out of saturation.

The above description is for a normal video signal; the presence of noise pulses more negative than the sync tip level would lower the gain to that level, thus disturbing the picture. A gated noise-inversion threshold is provide at the base of Q32 to compensate for these noise pulses. The threshold is about 1.5 V during trace time, but is reduced to about 1 V during coincidence of the sync and flyback pulses. When the video signal is more negative than the noise threshold, Q32 conducts and pulls the base and emitter of Q30 low. Without noise, Q23 conducts 0.5 mA with its collector at 7 V, which holds

Q22 in cutoff. Q23 has an emitter load provided by an external $1\text{ k}\Omega$ resistor and a series capacitor: when its base is switched low, its collector switches high. The resulting flow of current in Q23 overrides the normal negative-going pulse in the direct signal path and holds Q21 in saturation.

The video input to terminal 3 also operates the sync channel, beginning with Q31. Because Q32 is normally cut off, Q31 acts as an amplifier with a moderate gain to its collector, and a positive sync signal appears at terminal 4. If the noise pulse is more negative than the noise threshold at the base of Q32, the base of Q30 is pulled down as discussed above. In addition to operating the AGC noise inverter, the Q30 current passes through Q25 to the amplifier load resistor, R35, and cancels the potentially positive pulse at that point.

The positive sync signal at terminal 4 is coupled through an RC network to terminal 5 for sync separation. In essence, the network permits Q38 to clamp the positive peaks, so the most positive part of the signal is amplified by Q38 while the rest is beyond cutoff. The separated sync, a negative pulse at the collector of Q38, follows two paths. First, the sync operates an output driver to terminal

CIRCUIT DESCRIPTION (cont'd)

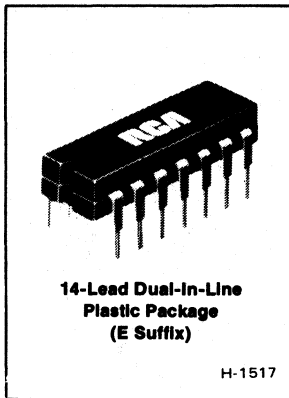
6, which drives the outboard diode phase detector. Second, the negative pulse cuts off the current through Q36, which otherwise holds Q35 in saturation, thus enabling a current in R41 to turn Q34 on and thereby shift the noise threshold voltage.

Terminal 7 receives a positive flyback pulse that supplies R41 with the signal to complete the coincidence gate that alters the noise threshold when sync and flyback pulses are in phase. The buffered and clipped flyback pulse also turns Q43 on, which, in conjunction with an external integrating capacitor, forms a sawtooth waveform. This sawtooth (at flyback rate) is phase compared with the sync pulse that was separated from the video input.

The phase detector works against an internal bias point brought out to terminal 10, and the phase detector output applied to terminal 11 is slightly positive or negative relative to terminal 10. This voltage differential with

terminal 10 determines the division of current between Q9 and Q10, which are part of the voltage controlled oscillator. The oscillator consists of the current source Q11, differential amplifier Q12 and Q13, and differential amplifier Q9 and Q10. The frequency is determined primarily by a series LC circuit connected between terminals 13 and 14 (terminals 12 and 13 have resistor loads to the positive supply). If the entire oscillator current passes through Q10 to terminal 13, the oscillator operates at the frequency at which the phase shift in the LC circuit is zero. If the current is sent through Q9 to terminal 12, however, it must go through an external capacitor between terminals 12 and 13 and then through the original LC circuit and the circuit is tuned differently. Intermediate proportions of current division will produce intermediate oscillator frequencies. The oscillator current output from Q12 provides base drive for the 31.5 kHz output at terminal 15.

CA3190E



TV Horizontal/Vertical Countdown Digital Sync System

Features:

- Dual-Mode operation:
 - 625-line standard and non-standard signals
- Automatic mode recognition
- Clock input
- Vertical ramp (sawtooth) generator
- Vertical amplifier
- Vertical blanking generator
- Horizontal drive pulse output
- Ratio-voltage regulator
- Excellent immunity to noise and interference
- Inherent interlace for standard signals
- Vertical-hold control eliminated
- Supply-voltage range = 8.6 to 14.2 V
- Rapid pull-in
- I²L logic

The RCA-CA3190* is a monolithic I²L integrated circuit TV digital sync system designed for use in 625-line applications. It features dual-mode operation and accepts either standard signals (B and G or equivalent)** or non-standard signals. An automatic mode-recognition system forces the CA3190 into the synchronous mode for standard signals or into the non-synchronous mode for non-standard sync signals. Other on-chip functional blocks include a vertical-ramp (sawtooth) generator, a vertical amplifier, a ratio voltage regulator, and a countdown and phasing circuit that eliminates the need for an external vertical-hold control.

The CA3190 is supplied in the 14-lead dual-in-line plastic package.

*Formerly RCA Developmental No. TA10692.
 **Refer to CCIR Standards.

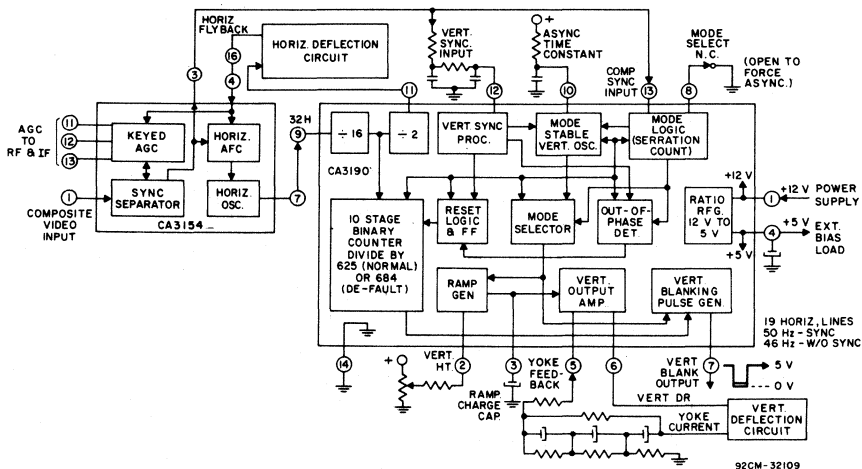


Fig. 1 - Functional block diagram of the CA3190 horizontal/vertical countdown integrated circuit.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE	15	V
DEVICE DISSIPATION:		
Up to $T_A = 70^\circ\text{C}$	530	mW
Above $T_A = 70^\circ\text{C}$	derate linearly at 6.7	mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:		
Operating	0 to 70	$^\circ\text{C}$
Storage	-55 to +150	$^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):		
At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case		
for 10 seconds max.	+265	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, all switches open unless otherwise specified.

See Fig. 2, Test Points 2 and 14 = Gnd

CHARACTERISTIC	TEST CONDITIONS	LIMITS		UNITS
		Min.	Max.	
Amplifier Gain, V6	S2,S5,S6 Closed, Note 1, Test pt. 1 = 12V, 16 = 1V _{RMS} at 1 kHz	0.178	3.16	V _{RMS}
Horizontal Frequency Divider Ratio, $f_9 \div f_{11}$	S3,S7,S8 Closed, Note 7, Test pt. 1 = 14.4V,	32	32	RATIO
Horizontal Pulse Width, Term. II	S3,S7,S8 Closed, Notes 9,10, Test pt. 1 = 8.4V	30	37	μs
	S3,S7,S8 Closed, Notes 9,10,11, Test pt. 1 = 14.4V	30	36	
Asynchronous Non-Coincident Frequency Divide Ratio, $f_9 \div f_3$	S3,S7,S8 Closed, Notes 9,12,13, 14,15, Test pt. 1 = 14.4V, 8 = 0.2V, 12 = 1.5V	10944	10944	RATIO
Ramp Charge Pulse Width, Term. 3	S3,S7,S8 Closed, Notes 13,15, Test pt. 1 = 14.4V, 8 = 0.2V, 12 = 1.5V	185	315	μs
Asynchronous Coincident Noise Immunity, Hold-Off Freq. Divider Ratio, $f_8 \div f_3$	Notes 9,12,13,15,16,17, Test pt. 1 = 14.4V, 8 = 0.2V	7872	7872	RATIO
Synchronous Divider Ratio, $f_9 \div f_3$	S3,S7,S8 Closed, Notes 9,13,15, 18,19, Test pt. 1 = 14.4V, 8 = 0.2V, 12 = 1.5V	10000	10000	RATIO
Ramp Charge Pulse Width, Term. 3	S3,S7,S8 Closed, Notes 9,10,13, 15,18,20, Test pt. 1 = 14.4V, 8 = 0.2V, 12 = 1.5V	192	192	CLOCKS
Vertical Blanking Pulse Width, Term. 7	S3,S7,S8 Closed, Notes 9,10,13, 15,18,21, Test pt. 1 = 14.4V, 8 = 0.2, 12 = 1.5V	608	608	CLOCKS

Linear Integrated Circuits

CA3190E

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, all switches open unless otherwise specified.

See Fig. 2, Test Points 2 and 14 = Gnd

CHARACTERISTIC	TEST CONDITIONS	LIMITS		UNITS
		Min.	Max.	
Mode Recognition Field Count, Freq. Divider Ratio, $f_g \div f_3$	S3,S7,S8 Closed, Notes 9,13, 14, 15, 22, Test pt. 1 = 14.4V, 8 = 0.2V, 12 = 1.5V			RATIO
	Initial Fields 8 Serrations	10000	10000	
	First Field, 7 Ser.	10000	10000	
	Second Field, 7 Ser.	10000	10000	
	Third Field, 7 Ser.	10000	10000	
	Fourth Field, 7 Ser.	10000	10000	
	Fifth Field, 7 Ser.	10000	10000	
	Sixth Field, 7 Ser.	10000	10000	
	Seventh Field, 7 Ser.	10944	10944	
	Eighth Field, 8 Ser.	10000	10000	
Confidence of Coincidence Field Count, Freq. Divider Ratio, $f_g \div f_3$	S3,S7,S8 Closed, Notes 9,13, 15,18,23, Test pt. 1 = 14.4V 8 = 0.2V			RATIO
	First Field	4200	4200	
	Second Field	10000	10000	
	Third Field	10000	10000	
	Fourth Field	10000	8000	
	Fifth Field	10000	10000	
	Sixth Field	10000	10000	
	Seventh Field	10000	10000	
	Eighth Field	10000	10000	
	Ninth Field	4200	4200	

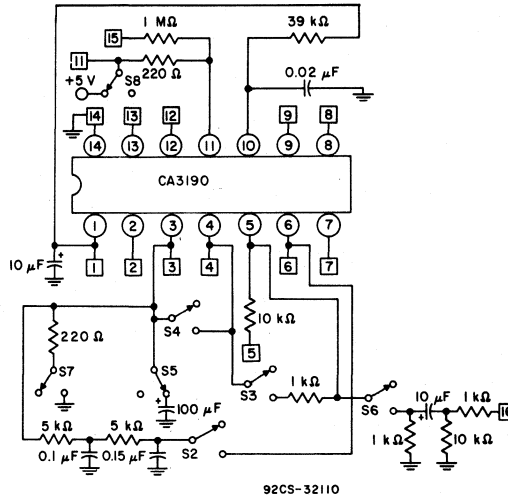
Notes:

1. Stop clock when terminal 7 is high
2. Stop clock when terminal 9 is low
3. Stop clock when terminal 9 is high
4. Stop clock when terminal 7 is low
5. Stop clock when terminal 11 is high
6. Stop clock when terminal 11 is low
7. Clock frequency = 600 kHz; clock amplitude: low $\leq 0.45\text{ V}$, high $\geq 0.95\text{ V}$ (5 V max.)
8. Frequency at terminal 9 (clock) divided by frequency at terminal 11 (hor. out)
9. Clock frequency = 500 kHz, clock amplitude same as in note 7
10. Pulse width measured at 2 V point on output waveform
11. Total capacity = 50 pF when measuring pulse width
12. Sync serrations = 8 (See Fig. 4)
13. Sync amplitude: low state $\leq 1.2\text{ V}$; high state $\geq 4\text{ V}$ (6 V max. with positive sync tips)
14. Frequency at terminal 9 (clock) divided by frequency at terminal 3 (ramp control)
15. Initialize or repeat initialization procedure before doing this test (See Fig. 2)
16. Apply a pulse 1 clock wide, 7808 clocks after first positive transition at terminal 3 (See Fig. 5)
17. Default count determined by $684 \times 16(H) = 10944$
18. Sync serrations = 8
19. Hold-off count determined by $492 \times 16(H) = 7872$
20. Number of clocks occurring within ramp gate period (See Fig. 6)
21. Number of clocks occurring during the blanking gate period (See Fig. 7)
22. This series of tests checks the mode recognition circuit. The first test after initialization applies 8 serrations at the sync input terminal. The IC should go to the synchronous count ratio of 10000. During the next seven fields only 7 serrations are applied. The CA3190 should maintain the synchronous count ratio of 10000 for the first six fields. At the seventh field the CA3190 should go to default count of 10944. The test concludes with an 8 serration input. The CA3190 should revert to a synchronous count of 10000 (See Fig. 8)
23. This test checks the operation of the out-of-sync detector by applying out-of-phase sync pulses to terminal 12. The CA3190 will count eight fields before resetting to the sync pulse (See Fig. 9)

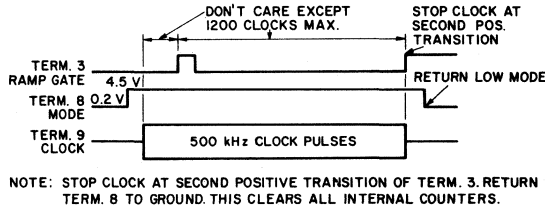
STATIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V^+ = 12\text{ V}$, Switches open unless otherwise specified. See Fig. 2. Test Points 2,8,12, and 14 grounded unless otherwise specified

CHARACTERISTIC	TEST CONDITIONS	CONNECT TEST POINTS AS SHOWN BELOW									LIMITS		UNITS
		TEST POINT NOS.									Min.	Max.	
		1	3	4	5	6	10	11	13				
Ratio Regulator Voltage, V_4 : Load	S2 Closed, Note 1	12V		-35 mA	2V						4.9	5.5	V
		14.4V			2V						5.8	6.8	
Vertical Blanking Output, V_7 : Unblanked	S2 Closed, Notes 1,4	12V		-35 mA	G						2.5	5	V
		12V			G						0.09	0.5	
Horizontal Output Voltage, V_{11} : High	Test pt. 15=8V, S2 Closed, Notes 5,6	14.4			G						7	8.1	V
		12V			G			20 mA			0.09	0.32	
Vertical Output Voltage, V_6 : Off	S4 Closed, Note 1	12V			G	1 mA					0.6	1.4	V
	S3 Closed, Note 1	12V	G			-20 mA					3.1	5.1	
Difference Voltage, V_3-V_5	S2 Closed, Note 1	12V			4V	-20 mA					-0.15	0.15	V
Supply Current, I1	S2 Closed, Note 1	14.4V			2V						10	35	mA
Clock Input Current, I9: Clock High	S2 Closed, Note 3	14.4V			2V						65	150	μA
	S2 Closed, Note 2	14.4V			2V						-7	7	
Composite Sync Input Current, I13: Sync High	S2 Closed, Note 3	12V			2V				4V		100	700	μA
		14.4V			2V				0V		-25	25	
Forced Asynchronous Current, I8	S2 Closed, Note 3, Test pt. 8 = 4.5V	12V			2V						100	700	μA
Ramp Current, I3	S3 Closed, Note 1, Test pt. 2 = 50 μA	12V	4.5V								45	57	μA
Δ Ramp Current, ΔI_3	S3 Closed, Note 1, Test pt. 2 = 50 μA	12V	1.5V								-3	3	μA
Async Time Constant Current, I10: Charge	S2 Closed, Note 4	12V			2V			3V			10	40	μA
		12V			2V			4.5V			1	5	
Vert. Sync. Input Current, I12: Normal	S2 Closed, Note 4, Test pt. 12 = 2.3V	12V			2V						75	300	μA
		12V			2V						0.1	3	
Overdrive	S2 Closed, Note 4, Test pt. 12 = 3V	12V			2V								mA

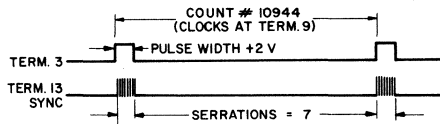
CA3190E



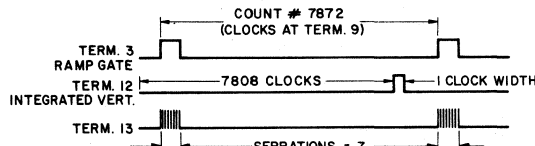
92CS-32110
Fig. 2 — Electrical characteristics test circuit.



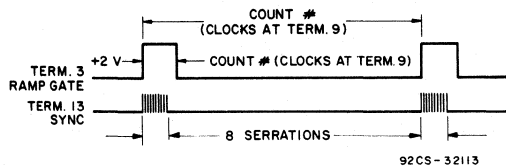
92CS-31682
Fig. 3 — Initialization timing diagram (applies to all tests referenced to Note 15).



92CS-32111
Fig. 4 — Asynchronous non-coincident divide ratio (applies to all tests referenced to Note 12).



92CS-32112
Fig. 5 — Asynchronous coincident noise immunity hold-off (applies to test referenced to Note 16).



92CS-32113
Fig. 6 — Synchronous non-coincident divider ratio and ramp gate pulse width (applies to test referenced to Note 20).

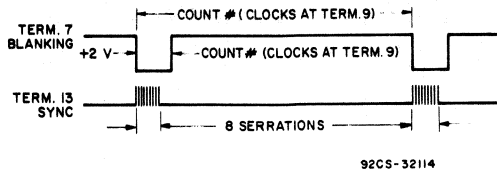


Fig. 7 — Blanking synchronous divider ratio and blanking pulse width (applies to test referenced to Note 21).

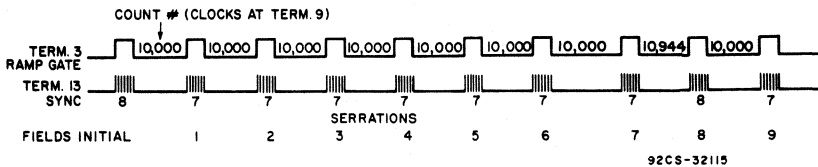


Fig. 8 — Mode recognition field count test (applies to test referenced to Note 22).

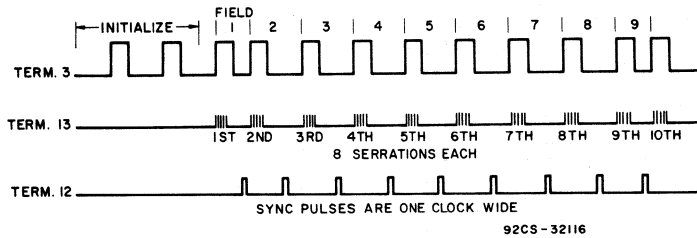


Fig. 9 — Out-of-sync detector test for confidence of coincidence field count at terminal 3 (applies to test referenced to Note 23).

Circuit Operation

Fig. 1 shows the major functional elements of the CA3190. An external oscillator (CA3154G) supplies an input to terminal 9 of the CA3190 that is 32 times the horizontal rate. An internal divide-by-16 counter converts this input ($32f_H$) to $2f_H$ for use elsewhere in the CA3190. This $2f_H$ signal is further divided to f_H , which is available at terminal 11 to drive the horizontal deflection circuits. A divide-by-625 counter further divides the $2f_H$ signal to generate the vertical ramp generator timing pulses and the vertical blanking pulse.

A phasing circuit (part of the mode recognition and vertical regeneration circuits) insures that the 625 counter is reset in coincidence with the vertical sync. It does this by comparing the internally generated vertical pulse with an external integrated vertical sync signal applied to terminal 12. The automatic mode recognition circuit forces the CA3190 into the synchronous mode for standard signals or into the non-synchronous mode for non-standard sync signals such as video games. An input control signal (or no connection) at terminal 8 places

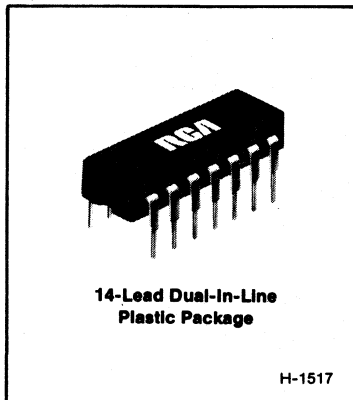
the CA3190 into non-synchronous operation.

The vertical retrace signal is converted to a ramp if a capacitor is connected between terminal 3 and ground. The slope of the ramp corresponds to vertical size and is controlled by changing the input current to terminal 2. The ramp is connected to the inverting input of a difference amplifier. The output of this amplifier is connected to terminal 6, and is used to drive the vertical output stage. The non-inverting input of the amplifier is at terminal 5, and a voltage derived from the yoke current may be applied to this terminal for improvement of linearity.

The pulse width of the vertical blanking signal at terminal 7 is 608 clocks wide in the synchronous mode, and is adjustable in width by changing the monostable rc network at terminal 10 for the non-synchronous mode.

The proportional voltage regulator output at terminal 4 is about 43% of the supply voltage at terminal 12. The maximum external load current is 35 mA peak.

CA3202E



TV Horizontal/Vertical Countdown Digital Sync System

Features:

- Automatic forced asynchronous mode to remove jitter
- Improved low voltage start-up operation
- Lower zero-state horizontal-drive pulse output
- Improved symmetry for horizontal-drive output
- Improved automatic standard operation
- Noise detector
- Handles standard NTSC and non-standard signals
- Automatic mode recognition
- Clock input
- Vertical ramp (sawtooth) generator
- Vertical amplifier
- Vertical blanking generator
- Horizontal drive pulse output
- Ratio-voltage regulator
- Inherent interlace for NTSC signals
- Vertical-hold control eliminated
- Supply-voltage range=10.8 to 13.2 V
- Rapid pull-in
- Co-channel sync lockout for NTSC signals
- β^2L logic

The RCA CA3202E is an improved version of RCA CA3157. In some video playback units, there are incorrect frequency relationships between horizontal and field frequencies. Automatic forced asynchronous mode eliminates jitter when equalizer pulses are correct, but these incorrect frequency relationships exist.

Automatic standard mode occurs upon detection of nine or more equalizing pulses during a six-line-width vertical driving period after seven fields of coincidence between integrated vertical (IV) sync and internal counter output. Standard mode is retained for seven fields of missing or mutilated vertical sync pulses.

If two or more noise pulses are detected at terminal 12 during a 384-line active scan time, a noise detector reverts the system to standard mode at the next field of coincidence (without the seven fields of coincidence delay). Thus, the unit stays in standard mode during tuner channel changes.

As in the CA3157, an automatic mode-recognition system places the unit in standard mode for NTSC signals or into non-synchronous mode for non-standard sync signals.

Fig. 1 shows that the chip includes a sawtooth generator, vertical amplifier, ratio-voltage regulator, and a countdown and phasing circuit that eliminates an external vertical hold control.

An external oscillator (CA3154) supplies an input to terminal 9 that is 32 times the horizontal rate. An internal divide-by-16 counter converts this input ($32f_H$) to $2f_H$ for use elsewhere. This $2f_H$ signal is further divided to f_H , which is available at terminal 11 to drive the horizontal deflection circuits. A divide-by-525 counter further divides the $2f_H$ signal to generate the vertical ramp generator timing pulses and the vertical blanking pulse.

A phasing circuit (part of the mode recognition and vertical regeneration circuits) insures that the 525 counter is reset in coincidence with the vertical sync. It does this by comparing the internally generated vertical pulse with an external integrated vertical sync signal applied to terminal 12. The automatic mode recognition circuit forces the

CA3202E into the standard mode for NTSC signals or into the non-synchronous mode for non-standard sync signals such as video games. An input control signal (or no connection) at terminal 8 places the CA3202E into non-synchronous operation.

A phasing and timing logic circuit checks to see if the line counter is in sync with the IV signal at terminal 12. Seven consecutive fields of in-phase coincidence with the IV signal are needed to achieve standard mode unless two or more noise pulses are de-detected at input terminal 12 during the active scan time. In this case, normal mode will be acquired in one field.

In the standard divide-by-525 mode, the integrated vertical pulse is used only to provide coincidence with the 545 count (counter preset=20, $545-20=525$) in the phase detector circuit. The vertical ramp is timed by the output of the 525 counter. In standard mode, the CA3202E will maintain the divide-by-525 count for six fields of lost or mutilated sync. If the seventh field does not have the correct coincidence, the unit will switch to non-standard mode. In this mode, the vertical sync is derived from the integrated vertical pulse on a field-to-field basis. A noise immunity of 384 lines is provided. In the absence of sync pulses, the count will be 684 instead of 525 so that rapid vertical capture may be achieved when sync is restored. Non-standard mode still may be selected by removing ground from terminal 8.

CA3202E

The vertical retrace signal is converted to a ramp signal if a capacitor is connected between terminal 3 and ground. The ramp's slope corresponds to vertical size and is controlled by changing the input current to terminal 2. The ramp is connected to the inverting input of a difference amplifier. The output of this amplifier, connected to terminal 6, is used to drive the vertical output stage. The non-inverting input of the difference amplifier is at terminal 5. A voltage derived from yoke current may be applied to this terminal for linearity improvement.

The pulse width of the vertical blanking signal at terminal 7 is 608 clocks wide in the synchronous mode, and is adjustable in width by changing the monostable rc network at terminal 10 for the non-synchronous mode.

The proportional voltage regulator output at terminal 4 is about 43% of the supply voltage at terminal 12. The maximum external load current is 20-mA peak.

The CA3202E is supplied in the 14-lead dual-in-line plastic package.

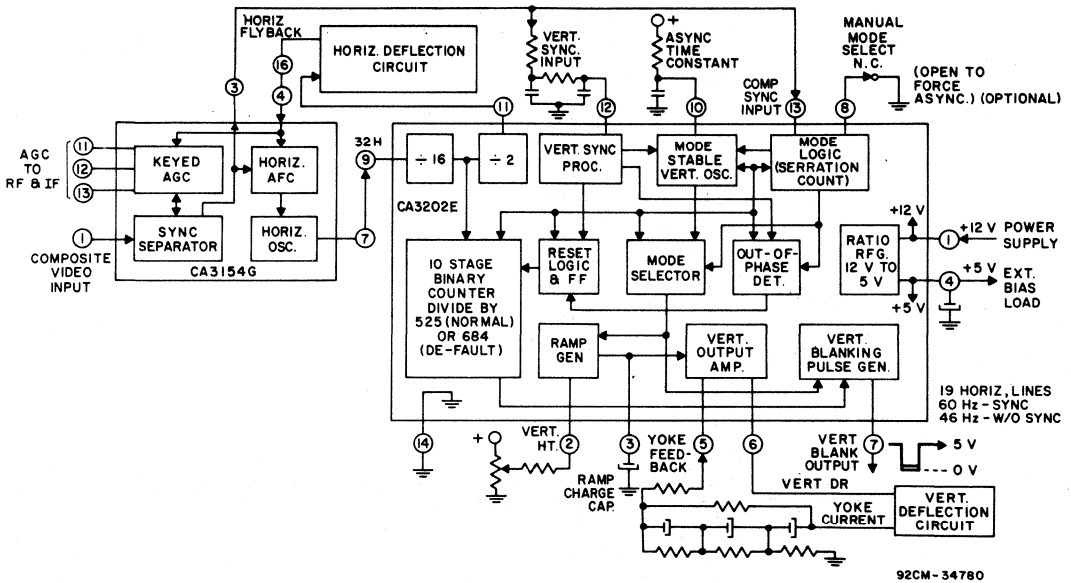


Fig. 1 - CA3202E horizontal/vertical countdown integrated circuit.

Linear Integrated Circuits

CA3202E

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE 15 V

DEVICE DISSIPATION:

Up to $T_A=70^\circ\text{C}$ 530 mW

Above $T_A=70^\circ\text{C}$ derate linearly at 6.7 mW/ $^\circ\text{C}$

AMBIENT TEMPERATURE RANGE:

Operating 0 to 70°C

Storage -55 to $+150^\circ\text{C}$

LEAD TEMPERATURE (DURING SOLDERING):

At distance $1/16 \pm 1/32$ in. (1.59 ± 0.79 mm) from case for 10 s max. $+265^\circ\text{C}$

ELECTRICAL CHARACTERISTICS at $T_A=25^\circ\text{C}$, all switches open unless otherwise specified.

See Fig. 2, Test Points 2 and 14=Gnd.

CHARACTERISTIC	TEST CONDITIONS	LIMITS		UNITS
		Min.	Max.	
Amplifier Gain, V6	S2,S5,S6 Closed, Note 1, Test pt. 1=12 V, 16=1 V_{RMS} at 1 kHz	0.178	3.16	V_{RMS}
Horizontal Frequency Divider Ratio, $f_g \div f_{11}$	S3,S7,S8 Closed, Note 7, Test pt. 1=14.4 V	32	32	RATIO
Horizontal Pulse Width, Term. 11	S3,S7,S8 Closed, Notes 9,10, Test pt. 1=8.4 V	28	34	μs
	S3,S7,S8 Closed, Notes 9,10,11, Test pt. 1=14.4 V	28	34	
Asynchronous Non-Coincident Frequency Divide Ratio, $f_g \div f_3$	S3,S7,S8 Closed, Notes 9,12,13,14,15, Test pt. 1=14.4 V, 8=0.2 V, 12=1.5 V	10944	10944	RATIO
Ramp Charge Pulse Width, Term. 3	S3,S7,S8 Closed, Notes 13,15, Test pt. 1=14.4 V, 8=0.2 V, 12=1.5 V	585	985	μs
Asynchronous Coincident Noise Immunity, Hold-Off Freq. Divider Ratio, $f_g \div f_3$	Notes 9,12,13,15,16,17, Test pt. 1=14.4 V, 8=0.2 V	7872	7872	RATIO
Synchronous Divider Ratio, $f_g \div f_3$	S3,S7,S8 Closed, Notes 9,13,15,18,19, Test pt. 1=14.4 V, 8=0.2 V, 12=1.5 V	8400	8400	RATIO
Ramp Charge Pulse Width, Term. 3	S3,S7,S8 Closed, Notes 9,10,13,15,18,20, Test pt. 1=14.4 V, 8=0.2 V, 12=1.5 V	190	194	CLOCKS
Vertical Blanking Pulse Width, Term. 7	S3,S7,S8 Closed, Notes 9,10,13,15,18,21 Test pt. 1=14.4 V, 8=0.2, 12=1.5 V	606	610	CLOCKS

**ELECTRICAL CHARACTERISTICS at $T_A=25^\circ\text{C}$, all switches open unless otherwise specified.
See Fig. 2, Test Points 2 and 14=Gnd.**

CHARACTERISTIC	TEST CONDITIONS	LIMITS		UNITS
		Min.	Max.	
Mode Recognition Field Count, Freq. Divider Ratio, $f_g \div f_3$ Synchronous to Non-Synchronous	S3,S7,S8 Closed, Notes 9,13,14,15,18,22, Test pt. 1=12.0 V, 8=0.2 V, 12=1.5 V			RATIO
	Initial Fields 9 Serrations	8400	8400	
	First Field, 8 Ser.	8400	8400	
	Second Field, 8 Ser.	8400	8400	
	Third Field, 8 Ser.	8400	8400	
	Fourth Field, 8 Ser.	8400	8400	
	Fifth Field, 8 Ser.	8400	8400	
	Sixth Field, 8 Ser.	8400	8400	
Mode-Recognition Field Count, Freq. Divider Ratio, $f_g \div f_3$ Non-Synchronous to Synchronous	S3,S7,S8 Closed, Notes 9,13,15,18,23, Test pt. 1=12.0 V, 8=0.2 V			RATIO
	First Field	8384	8384	
	Second Field	8384	8384	
	Third Field	8384	8384	
	Fourth Field	8384	8384	
	Fifth Field	8384	8384	
	Sixth Field	8384	8384	
	Seventh Field	8384	8384	
	Eighth Field	8400	8400	
Fast Standard-Mode Resynchronization	S3,S7,S8 Closed, Notes 9,13,15, Test pt. 1=12.0 V, 8=0.2 V			

NOTES:

- Stop clock when terminal 7 is high.
- Stop clock when terminal 9 is low.
- Stop clock when terminal 9 is high.
- Stop clock when terminal 7 is low.
- Stop clock when terminal 11 is high.
- Stop clock when terminal 11 is low.
- Clock frequency=600 kHz; clock amplitude: low $\leq 0.45\text{ V}$, high $\geq 0.95\text{ V}$ (5 V max.).
- Frequency at terminal 9 (clock) divided by frequency at terminal 11 (hor. out).
- Clock frequency=500 kHz, clock amplitude same as in Note 7.
- Pulse width measured at 2 V point on output waveform.
- Total capacity=50 pF when measuring pulse width.
- Sync serrations=8 (see Fig. 4).
- Sync amplitude: low state $\leq 1.2\text{ V}$; high state $\geq 4\text{ V}$ (6 V max. with positive sync tips).
- Frequency at terminal 9 (clock) divided by frequency at terminal 3 (ramp control).
- Initialize or repeat initialization procedure before doing this test (see Fig. 2).
- Apply a pulse 1 clock wide, 7808 clocks after first positive transition at terminal 3 (see Fig. 5).
- Default count determined by $684 \times 16(H)=10944$.
- Sync serrations=9.
- Hold-off count determined by $492 \times 16(H)=7872$.
- Number of clocks occurring within ramp gate period (see Fig. 6).
- Number of clocks occurring during the blanking gate period (see Fig. 7).
- This series of tests checks the mode recognition circuit. The first test after initialization applies 9 serrations at the sync input terminal. The IC should go to the synchronous count ratio of 8400. During the next seven fields only 8 serrations are applied. The CA3202E should maintain the synchronous count ratio of 8400 for the first six fields. At the seventh field the CA3202E should go to default count of 10944. The test concludes with a 9-serration input. The CA3202E should revert to a synchronous count of 8400 (see Fig. 8).
- This test checks the operation of the out-of-sync detector by applying out-of-phase sync pulses to terminal 12. The CA3202E will count eight fields before resetting to the sync pulse (see Fig. 9).
- Initialize by 8384 sync for eight fields before test.
- This test verifies the operation of the fast resync performance by simulating a noise pulse (5 to 50 clocks wide) applied to the I.V. terminal 4000 to 6000 clocks (8 ms to 12 ms) after I.V. sync. Initialize to non-sync mode before performing this test. The IC should resync in the next field and be maintained for the standard confidence count of seven fields.

Linear Integrated Circuits

CA3202E

STATIC ELECTRICAL CHARACTERISTICS at $T_A=25^\circ\text{C}$, $V^+=12\text{ V}$, Switches open unless otherwise specified.
See Fig. 2. Test Points 2, 8, 12 and 14 grounded unless otherwise specified.

CHARACTERISTIC	TEST CONDITIONS	CONNECT TEST POINTS AS SHOWN BELOW								LIMITS		UNITS	
		TEST POINT NOS.								Min.	Max.		
		1	3	4	5	6	10	11	13				
Ratio Regulator Voltage, V4: Load	S2 Closed, Note 1	12V		-20 mA	2V						4.9	5.5	V
		14.4V			2V						5.8	6.8	
Vertical Blanking Output, V7: Unblanked	S2 Closed, Notes 1, 4	12V		-20 mA	G						2.5	5	V
		12V			G						0.09	0.5	
Horizontal Output Voltage, V11: High	Test pt. 15=8V, S2 Closed, Notes 5, 6	14.4			G						7	8.1	V
		12V			G			20 mA			0	0.12	
Vertical Output Voltage, V6: Off	S4 Closed, Note 1	12V			G	1 mA					0.6	1.4	V
		12V	G			-20 mA					3.4	5.1	
Difference Voltage, V3-V5	S2 Closed, Note 1	12V			4V	-20 mA					-0.15	0.15	V
Supply Current, I ₁	S2 Closed, Note 1	14.4V			2V						10	35	mA
Clock Current, I _g : Low	Test pt. 9=GND S2 Closed, Note 2	14.4V			2V						-180	-70	μA
Voltage, V _g	S2 Closed, Note 3	14.4V			2V						—	0.75	V
Composite Sync Input Current, I ₁₃ : Sync High	S2 Closed, Note 3	12V			2V			4V			100	700	μA
		14.4V			2V			0V			-25	25	
Forced Asynchronous Current, I _g	S2 Closed, Note 3, Test pt. 8=4.5V	12V			2V						1	3.2	mA
Ramp Current, I ₃	S3 Closed, Note 1, Test pt. 2=50 μA	12V	4.5V								45	57	μA
Δ Ramp Current, ΔI ₃	S3 Closed, Note 1, Test pt. 2=50 μA	12V	1.5V								-3	3	μA
Async Time Constant Current, I ₁₀ : Charge	S2 Closed, Note 4	12V			2V		3V				10	40	μA
		12V			2V		4.5V				1	5	
Vert. Sync. Input Current, I ₁₂ : Normal	S2 Closed, Note 4, Test pt. 12=2.3V	12V			2V						-0.1	5	μA
		12V			2V						0.1	3	
Overdrive	S2 Closed, Note 4, Test pt. 12=3V	12V			2V						0.1	3	mA

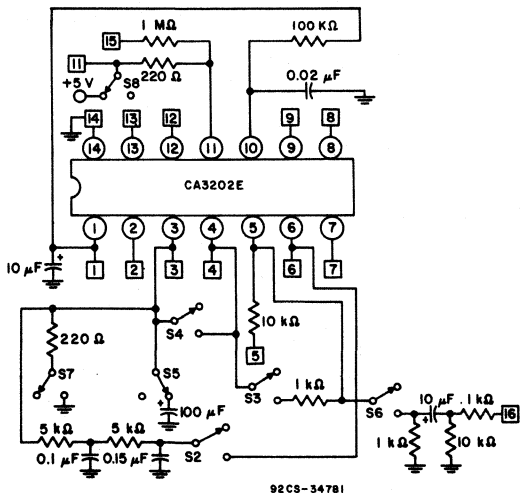
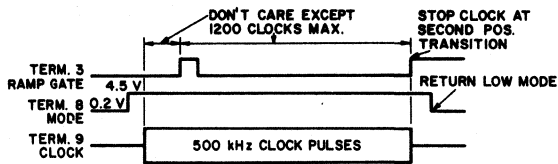


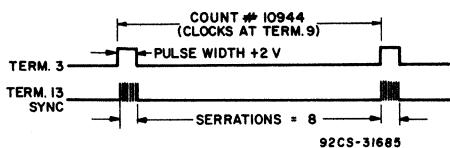
Fig. 2 - Electrical characteristics test circuit.



NOTE: STOP CLOCK AT SECOND POSITIVE TRANSITION OF TERM. 3. RETURN TERM. 8 TO GROUND. THIS CLEARS ALL INTERNAL COUNTERS.

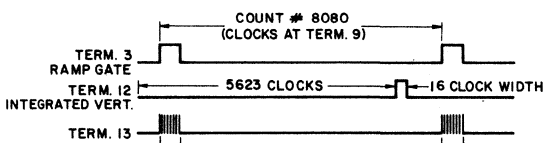
92CS-31682

Fig. 3 - Initialization timing diagram (applies to all tests referenced to Note 15).



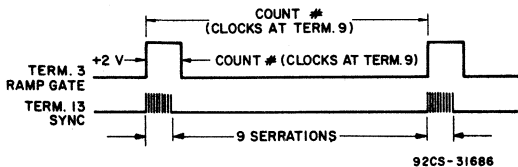
92CS-31685

Fig. 4 - Asynchronous non-coincident divide ratio (applies to all tests referenced to Note 12).



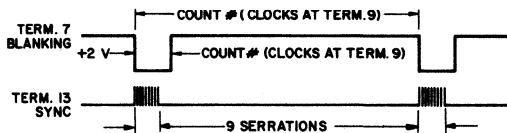
92CS-34782

Fig. 5 - Synchronous non-coincident noise recovery (fast resync).



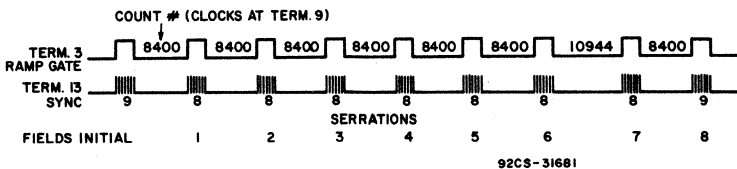
92CS-31686

Fig. 6 - Synchronous non-coincident divider ratio and ramp gate pulse width (applies to test referenced to Note 20).



92CS-31687

Fig. 7 - Blanking synchronous divider ratio and blanking pulse width (applies to test referenced to Note 21).



92CS-31681

Fig. 8 - Mode recognition field count test (applies to test referenced to Note 22).

CA3202E

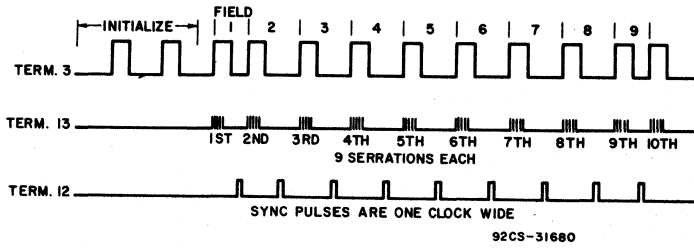
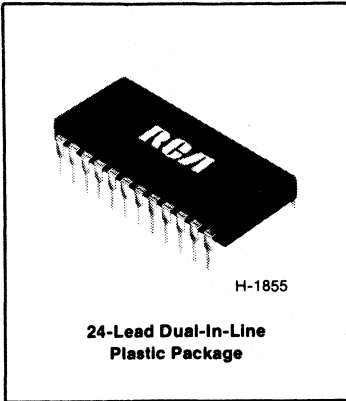


Fig. 9 - Out-of-sync detector test for confidence of coincidence field count at terminal 3 (applies to test referenced to Note 23).



TV Horizontal/Vertical Countdown Digital Sync System

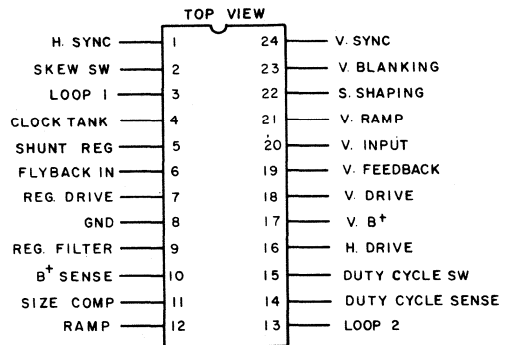
For 525-Line (CA3210E) or 625-Line (CA3223E) Operation

Features:

- Horizontal Driver
- Two Phase-Lock Loops
- Horizontal Oscillator
- Vertical Countdown
- Vertical Blanking
- Vertical Ramp Generator
- Pulse-Width Voltage Regulator
- Tape-Recorder Skew Compensation
- Internal Shunt Regulator

The RCA-CA3210E and CA3229E* are MSI integrated-circuit digital sync systems, designed for use in consumer TV applications which combine horizontal oscillator and vertical countdown sections, as well as a pulse-width voltage-regulator driver for color or monochrome receivers. They feature dual-mode operation and accept either standard signals or nonstandard signals. An automatic mode-recognition system forces the operation into the nonsynchronous mode for non-standard sync signals. The CA3210E is intended for use with 525-line systems and the CA3223E is intended primarily for use with 625-line systems. The CA3223E will also operate in the direct sync mode with 525-line signal sources.

The CA3210E and CA3223E are supplied in the 24-lead dual-in-line plastic package.



92CS-34950

TERMINAL DIAGRAM

* Formerly RCA Dev. Type Nos. TA10955 and TA11324, respectively.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY:

- Terminal 17 10 V
- Terminal 22 15 V
- Terminal 5 — Shunt Regulator 30 mA

DEVICE DISSIPATION:

- Up to +70°C 695 mW
- Above +70°C Derate linearly at 8.7 mW/°C

AMBIENT TEMPERATURE RANGE:

- Operating 0 to +70°C
- Storage -55 to +150°C

LEAD TEMPERATURE (DURING SOLDERING):

- At distance 1/16 ± 1/32 in. (1.59 ± 0.79 mm) from case for 10 s max. +265°C

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CA3210E, CA3223E

ELECTRICAL CHARACTERISTICS at $T_A = +25$ to $+70^\circ\text{C}$

See Fig. 3, Test Points 4 and 18=27 V, Test Point 16=2.3 V, and Test Point 20=10 V.

CHARACTERISTIC	TEST CONDITIONS	LIMITS		UNITS
		Min.	Max.	
Supply Current	Note 1, Test pt. 5=9 V, Test pt. 4=adjusted	8	16	mA
Shunt Regulator Output	Test pt. 5	8.7	11	V
4fH Coincidence	Note 2, Test pin 21	24	45	μs
V. Count (+262.5)	* Note 3, Test pin 21	16.6	16.7	ms
V. Count (+312.5)	**	19.9	20.1	
V. Count 7 Fields after Loss of Sync:	Note 4, S1=2, Test pin 21	16.6	16.7	
(+262.5)				
(+312.5)	**	19.9	20.1	
V. Count 8 Fields after Loss of Sync:	Note 5, S1=2, Test pin 21	18.7	18.9	
(+296)				
(+232.5)	**	22	22.2	
V. Count Low (+232)	Note 6, S1=2, Test pin 21	14.6	14.9	
(+232.5)		**	14.7	
V. Ramp Pulse Width at 7 V	Note 7, Test pin 21	503	516	μs
		**	506	
V. Blanking Pulse Width	Note 8, Test pin 23	1.140	1.148	ms
		**	1.148	
V. Blanking Sat. Voltage	Note 9, Test pin 21	1.2	1.8	V
V. Sync SVC SW.	Note 10, Test pt. 20=0.7 V, Test pin 21	12	14	
Vertical Loop Gain:	Note 11(a),(b)			
Low	Test pin 18=0.3 V	11	11.7	
Medium	Test pin 18=4.5 V	10.89	11.81	
High	Test pin 18=8 V	10.89	11.85	
Regulator Driver Out	Test pin 7	6.2	7.5	
Horizontal Pulse Width	Note 12, Test pin 16	31.5	34.6	ns
		**	31.7	
Horizontal Drive Shutdown	Note 13, Test pin 16, Clock disabled	4.9	5.1	V
Horizontal Drive Sat. Voltage	Note 14, Test pin 16 at 15 mA	—	0.42	
Nominal Loop Phase	Note 15, Test pin 16	11.25	13.6	ns
Ramp Voltage (p-p)	Test pin 12	3.8	7.5	V_{p-p}

*CA3210E—525-Line system.

**CA3223E—625-Line system.

NOTES:

- Adjust 27-V supply for pin 5 voltage=9 V \pm 0.1 V and measure current into pin 5.
- Measure of the time delay between the output pulse at pin 21 and the input vertical sync at J1.
- Measure the period of the waveform at pin 21. The frequency at pin 16 should be 262.5* or 312.5** times the frequency at pin 21. This corresponds to a frequency of 59.939* or 50.000** Hz at 21 when 16 is 15734* or 15625** Hz.
- Remove vertical sync (SW1=2), and remeasure period of waveform at pin 21 6 fields later (100* or 120** ms). Period should remain the same as in previous test.
- Keep vertical sync off and remeasure period of waveform at pin 21 after 2 additional fields. The frequency at pin 16 should be 296* or 346** times the frequency at pin 21.
- With no vertical sync and pin 24 connected through 10 K Ω to +5 V, measure the period of the waveform at 21. The frequency at pin 16 should be 232* or 232.5** times that at pin 21.
- Measure pulse width of waveform in pin 21 at +7-V trip points.
- Measure pulse width at pin 23 at 4-V trip point.

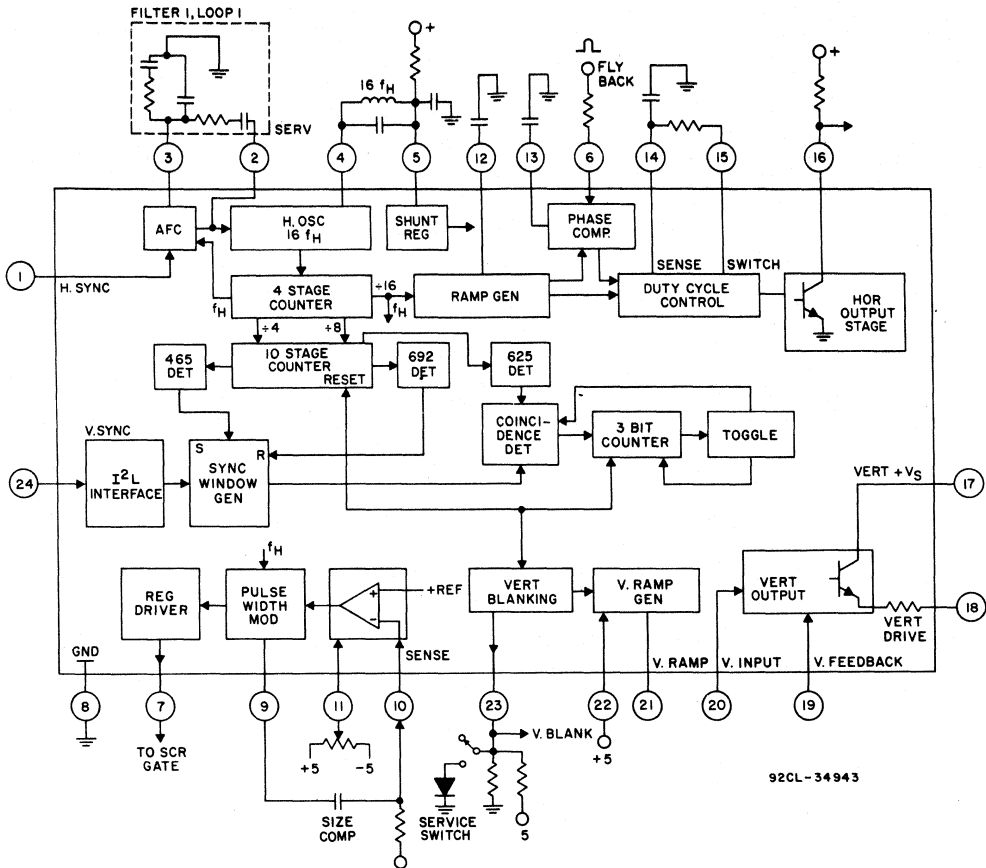


Fig. 1 - Functional block diagram of the CA3210E (525 line).

NOTES: (Cont'd)

9. Measure voltage at pin 21 when pin 23 is at low state. Clock may be stopped during measurement or measurement may be made on the "fly".
10. Set test point 20 to 0.7 V. Measure voltage at pin 21.
11. (a) Adjust test point 16 until pin 18 is 0.3 V. Measure voltage at pin 19.
(b) Adjust so that the voltage on pin 18 is 4.5 and 8.0 V, respectively.
12. Measure width of negative-going pulse at pin 16 at the 2-V level.
13. When pin 16 goes low, disable clock by applying 18 V. The purpose of this test is to verify that pin 16 will then go from low to high with the clock (pin 14) disabled.
14. Measure amplitude of pulse at pin 16 at its low state.
15. Measure delay of horizontal sync pulse (positive leading edge) with respect to the positive leading edge of pin 16.

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CA3210E, CA3223E

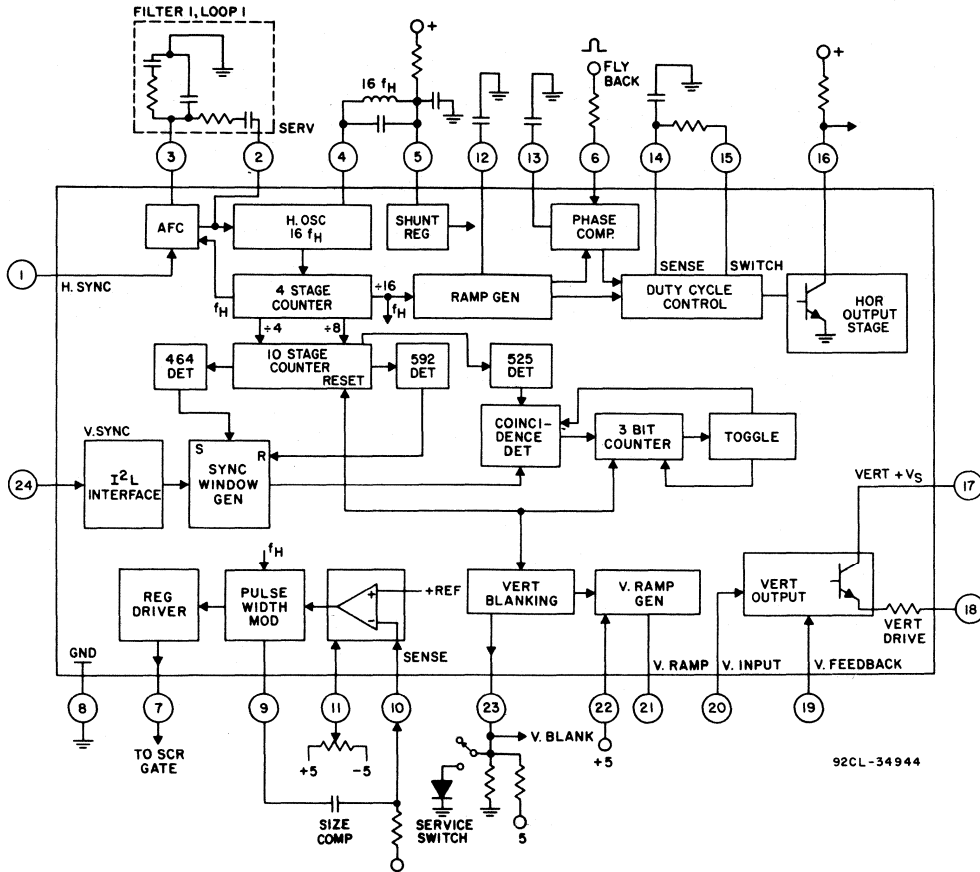


Fig. 2 - Functional block diagram of the CA3223E (625 line).

Horizontal/Vertical Processor

Circuit Operation

Figs. 1 and 2 of the block diagrams show the major functional elements of the RCA-CA3210E and CA3223E.

The master oscillator operates at 16 times the horizontal rate, f_H , as determined by an external LC tank connected between pins 4 and 5. The master oscillator is divided by 4, 8, and 16. The divide by 16 output is used to compare its phase with the incoming horizontal synchronization signal in the first APC loop which acts to synchronize the system. This output is also used to generate a horizontal ramp

whose output is used to control the phase of the horizontal output pulse with respect to a flyback pulse input in the second APC loop. The deviation of the horizontal output pulse is adjusted and then connected to the horizontal driver stage. The divide by 4 and 8 outputs are used to drive a 10 section counter for the vertical circuits. The use of the countdown system and associated logic circuits assures good noise immunity and the absence of a vertical hold control in the TV receiver.

CA3210E, CA3223E

As shown in Figs. 1 or 2 the 464th (CA3210E) or 465th (CA3223E) clock pulse is used to set a SYNC WINDOW generator. If the incoming SYNC signal occurs at the same time the 525th (CA3210E) or 625th (CA3223E) clock pulse occurs, the YES output of a coincidence gate is used to reset a 3-bit counter and to generate the start of vertical blanking and vertical sweep. If the incoming SYNC pulse is removed (by noise, for example), the 10-stage counter will continue to provide an output pulse at the 525th (CA3210E) or 625th (CA3223E) clock but the 3-bit counter will count the number of fields where no coincidence occurred. If incoming SYNC is regained before the 3-bit counter accumulates 8 fields, the 3-bit counter will reset and normal action will continue. If no coincidence is detected in 8

sequential fields, the 3-bit counter energizes the toggle which shifts the mode of operation from countdown to synchronization.

In the sync mode, vertical scan is initiated by the sync pulse. If no sync pulse is present, the system will free run at a frequency determined by the 592 (CA3210E) or 692 (CA3223E) count. A non-standard sync signal circuit operates if the incoming sync occurs regularly between 464 (CA3210E) or 465 (CA3223E) and 592 (CA3210E) or 692 (CA3223E) counts.

The divide by 16 output is also used in the pulse width modulator which generates a triggered constant pulse width signal which in turn drives the deflection circuit.

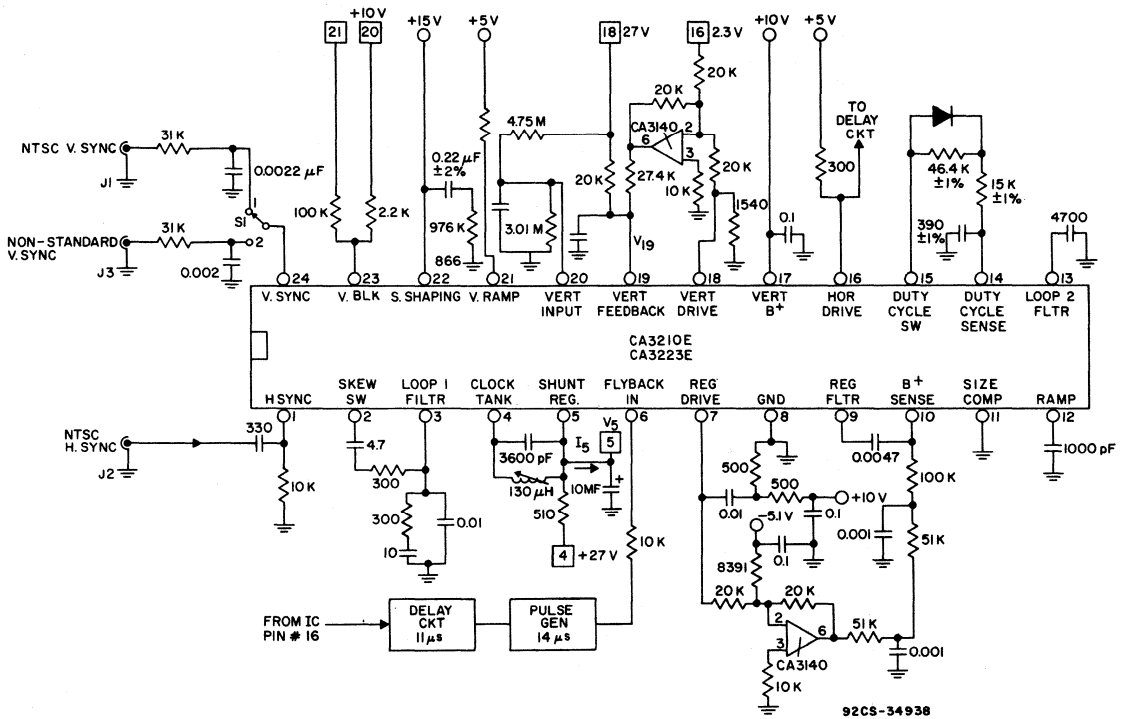


Fig. 3 - Testing circuit.

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CA3210E, CA3223E

Circuit Description

Start-up Circuit

The start-up circuit provides power to the integrated circuit at turn-on until horizontally derived B+ is sufficient to power the chip. The start-up circuit protects the horizontal system of the TV receiver by insuring the IC is in the correct mode by delaying operation until the chip supply voltage has reached 8.0 V. After the circuit starts, should the chip supply decrease to 4.0 V, the start-up circuit will turn the IC off.

Skew Switch

A frequency selector circuit is used to route two frequency signals to the AFC (see Figs. 1 and 2). Vertical signals control both the selector circuit and the external Filter 1 time constants. During most of the vertical scan time, signal f_H is routed to AFC and the Filter 1 time constant is selected for a slow loop 1 response time. For the remaining part of the vertical scan, signal $2f_H$ is fed to the AFC and the Filter 1 time constant is selected to give the loop a fast response time. This dual time constant feature allows the system to phase synchronize rapidly with non-standard signals generated by equipment such as a VCR.

Internal Shunt Regulator

The shunt regulator maintains the IC's main supply rail at constant voltage. As the voltage V+ (Fig. 4) increases from zero, the zener voltage eventually becomes conductive, and current flows through R50, R51, and R52. As the voltage across R51 increases, transistor Q119 becomes conductive, maintaining a fixed voltage between the collector and emitter of Q119. Increasing voltage V+ still further increases the voltage across resistor R52, eventually turning on Q120. At this point, voltage V+ becomes regulated due to the varying conduction of shunt transistor Q120.

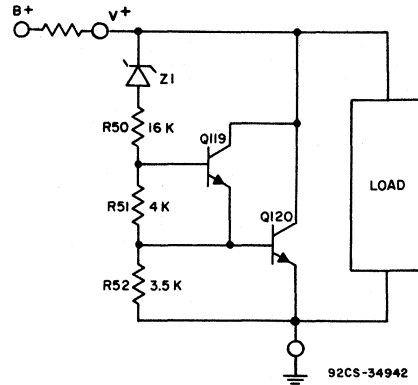


Fig. 4 - Shunt regulator.

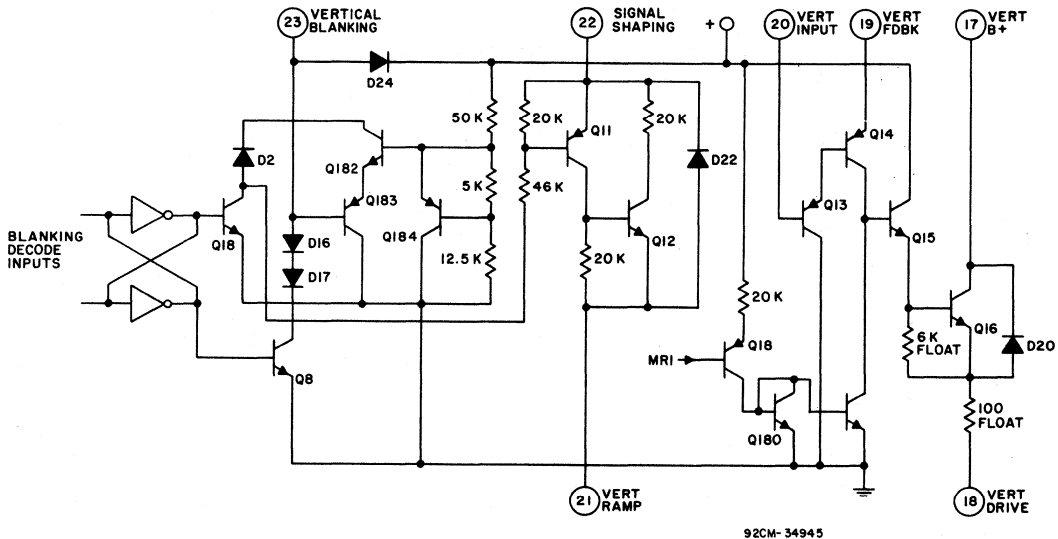


Fig. 5 - Vertical system signals.

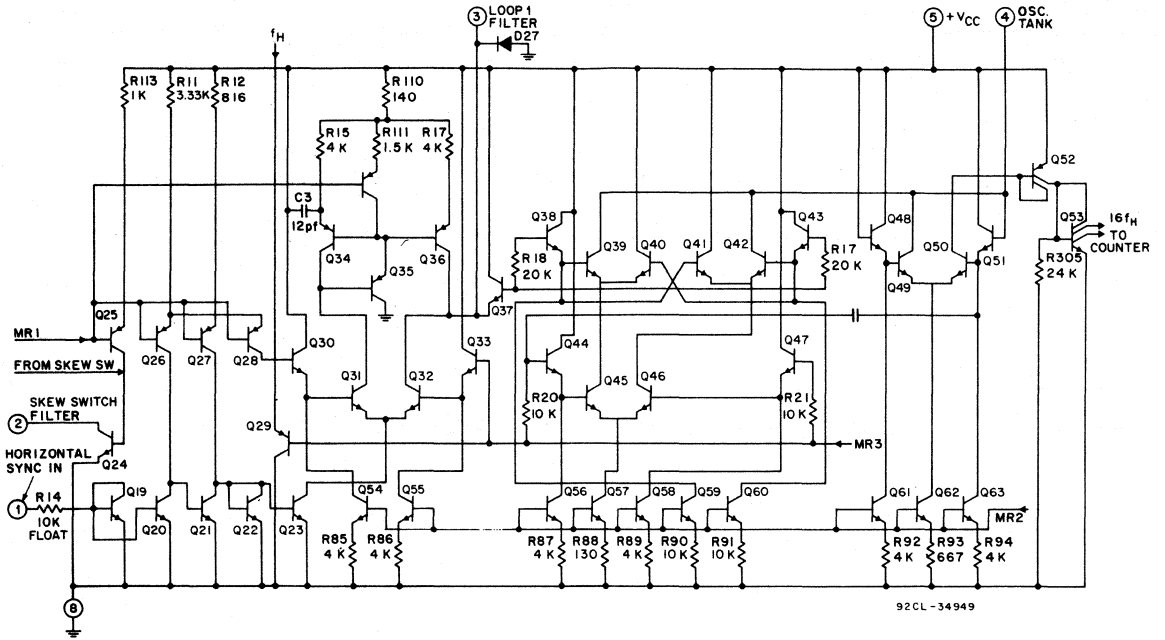


Fig. 6 - 1st loop phase detector of master oscillator.

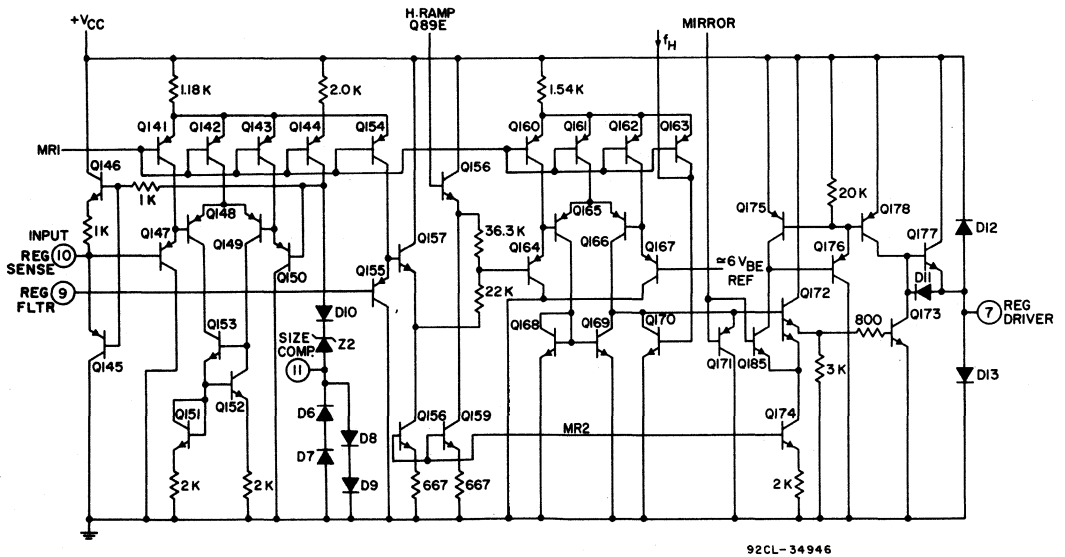


Fig. 7 - Regulator driver and pulse width modulator.

CA3210E, CA3223E

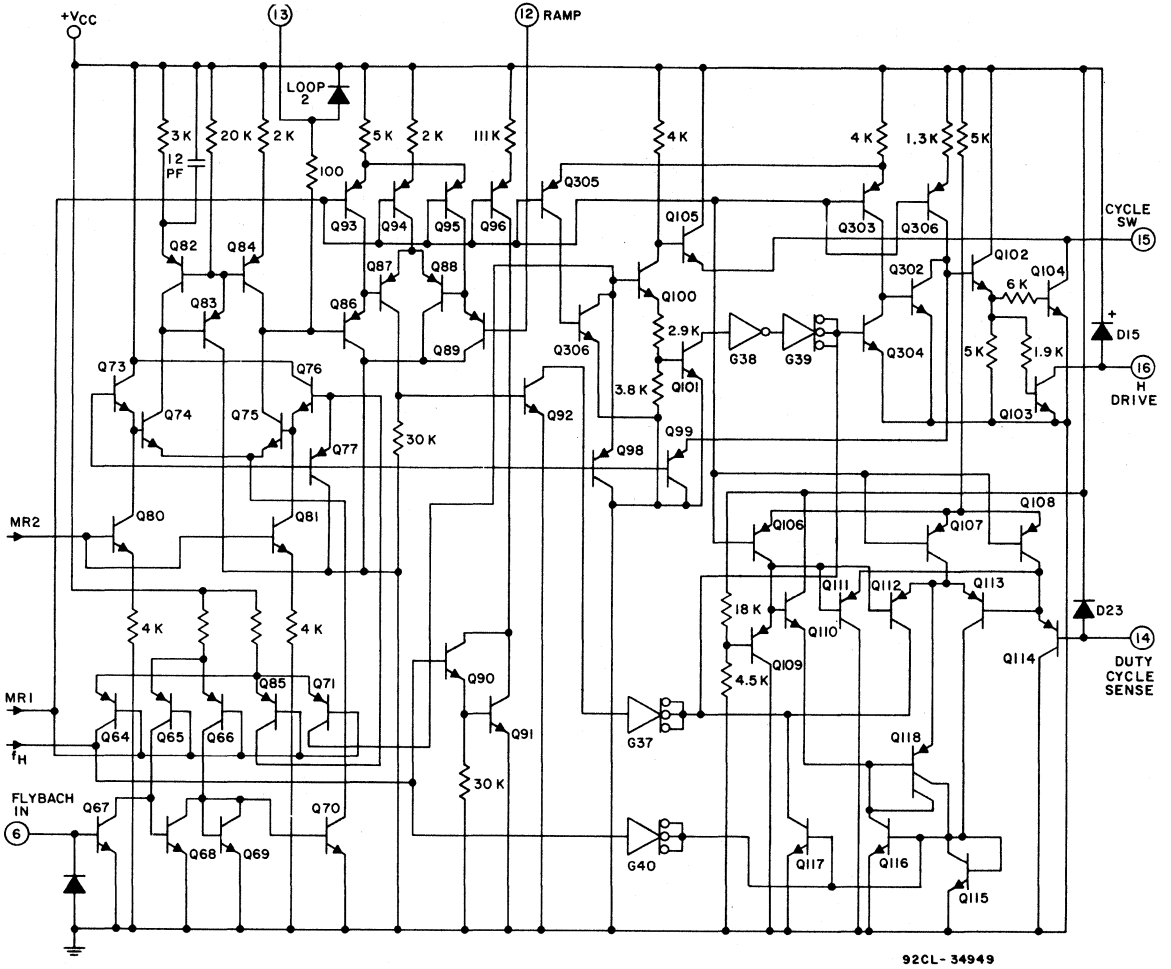


Fig. 8 - Horizontal ramp, control, and drive.

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CA3210E, CA3223E

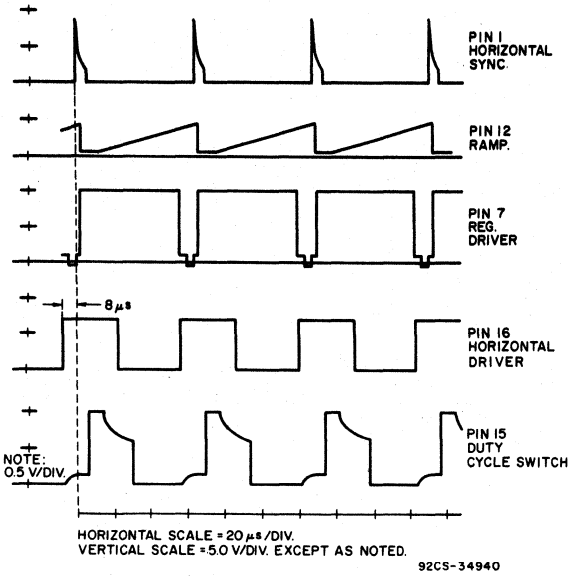


Fig. 10 - Timing relationship between various waveforms for typical circuit application.

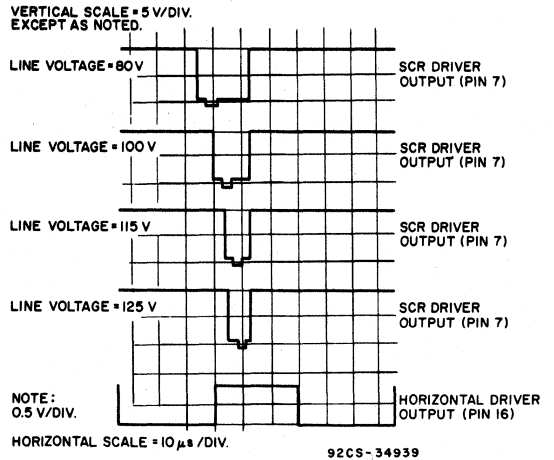


Fig. 11 - Relationship between SCR driver output and horizontal driver output vs. line voltage.

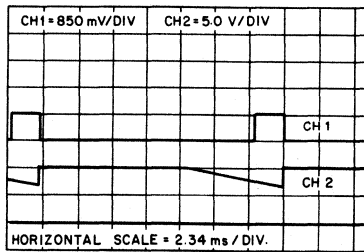
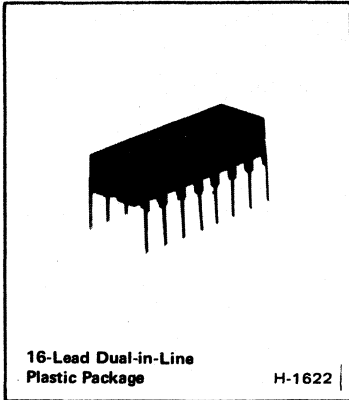


Fig. 12 - Relationship between the vertical sync pulse and the vertical ramp.



TV Signal Processors ("Jungle" Circuits)

For Color and Monochrome Receivers

FEATURES:

- Internal impulse noise processing
- Sync separator — low impedance, dual polarity
- Strobed AGC system ■ IF AGC output
- Delayed outputs for forward or reverse AGC tuners
- Automatic noise threshold and AGC detector level control
- High-impedance video input
- Low-impedance video output
- Choice of external time constants for sync separator
- Negative power supply not required
- RF AGC delay externally controlled

The RCA-CA3120E and CA3142E are monolithic silicon integrated circuit TV signal processors for use in color or monochrome receivers. These circuits provide low-impedance video output signals, stripped synchronization signals in both polarities, and AGC output signals for IF (reverse) and tuner (forward and/or reverse).

The circuit designs of the CA3120E and CA3142E feature impulse noise inversion, delay techniques to reduce the deleterious effects of impulse noise in the receiver AGC and sync circuits. In addition, they incorporate standard AGC strobing techniques. The AGC noise lockout circuit is deleted in the CA3142E.

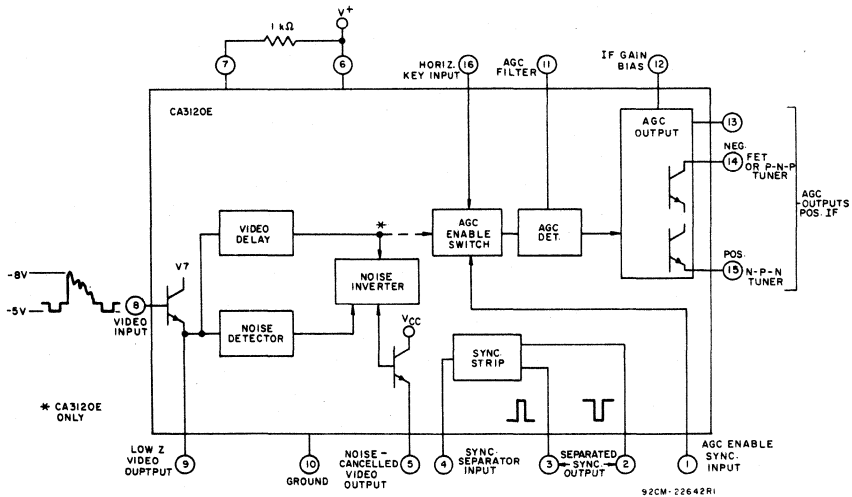


Fig. 1 — Simplified block diagram of the CA3120E and CA3142E.

Linear Integrated Circuits

CA3120E, CA3142E

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, Supply Voltage (V^+) = 24 V and Referenced to Test Circuits and Test Conditions (Figs. 6, 7, and 8).

CHARACTERISTICS	TERMINAL MEASURED AND SYMBOL	CA3120E CA3142E LIMITS			UNITS
		Min.	Typ.	Max.	
Supply Current (Pulse Test)	I_{T24}	20	—	40	mA
AGC Threshold (Sync Tip Level at Video Input)	V_{TH}	4.5	—	5.5	V
Video Input Amplitude (White Positive)	V_8	—	3	—	V _{p-p}
Video Output Amplitude (Low Impedance)	V_9	—	3	—	V _{p-p}
Noise Cancelled Video Output at V_{TH} (Black Positive, Gain $\cong 2$)	V_5	3.6	—	9.2	V
AGC to Noise Separation	V_{TH} (SEP)	1.1	—	2.2	V
Sync Input Current for Full Amplitude Outputs	I_4 (ON)	—	—	100	μA
Maximum Leakage Current at Terminal 4	I_4 (OFF)	—	—	± 6	μA
<u>Sync Outputs:</u>					
Negative Sync Low	$V_{2(L)}$	0	—	2.6	V
Negative Sync High	$V_{2(H)}$	23.8	—	24	V
Positive Sync Low	$V_{3(L)}$	0	—	0.2	V
Positive Sync High	$V_{3(H)}$	20.1	—	24	V
<u>AGC Filter:</u>					
Charge Current (Pulse Test)	$I_{11(CH)}$	12	—	36	mA
Discharge Current	$I_{11(DISCH)}$	1.1	—	2.6	mA
Leakage Current	$I_{11(LEAK)}$	—	—	± 6	μA
<u>AGC Enable:</u>					
Horizontal Keying	V_{16} (ON)	3	—	6	V
Negative Sync Input Current	I_1 (ON)	—	1	—	mA
Maximum IF Gain-Clamp Voltage	V_{11}	4.8	—	5.7	V
Maximum IF Gain Bias	V_{12}	4.2	—	5.2	V
<u>IF AGC Voltage:</u>					
Low	V_{13} (LOW)	0	—	3.3	V
High	V_{13} (HIGH)	5.7	—	6	V
<u>Tuner Currents:</u>					
Reverse AGC (FET) OFF Current	I_{14} (OFF)	—	—	± 6	μA
Reverse AGC (FET) ON Current	I_{14} (ON)	1.8	—	5.5	mA
Forward AGC (n-p-n) OFF Current	I_{15} (OFF)	—	—	± 6	μA
Reverse AGC (n-p-n) ON Current	I_{15} (ON)	4.5	—	15	mA
Internal Noise-Lockout Time (CA3120E only)	T	1	—	63	μs

CIRCUIT DESCRIPTION*

An AGC sample-and-hold system generates control voltages proportional to the video level. The sync-tip voltage is compared to an internal reference voltage during the horizontal synchronization (retrace) interval. The control voltages (AGC outputs) are supplied to the tuner's RF stage and the IF amplifier to maintain the video level at a constant value.

The composite positive and negative output sync signals are developed across a low impedance source (totem-pole circuit) at an amplitude of approximately 20 volts peak-to-peak.

Video Chain and Impulse Noise Inverter — The input video signal applied at Terminal 8 is white "positive" with a required amplitude in the range of 2 to 4 volts. The DC level of the sync peaks, AGC threshold voltage (V_{TH}) is approximately 5 volts. The level is maintained at 5 volts by the AGC loop in the circuit, comprised of the CA3120E or CA3142E and the TV receiver RF and IF amplifiers. A low source impedance video signal is available from the emitter of Q1 (Terminal 9 in Fig.2). The external resistor (R_{X1} in Fig.9) reduces the dissipation of Q1. The emitter-follower output of Q1 is directly coupled to a differential comparator stage (Q2, Q3). Unless a negative-going pulse is present, Q2 functions as an emitter follower and also cuts off transistors Q3, Q5, and Q12.

The output of Q2 is applied through a signal delay network, consisting of transistor Q60 and associated resistors, to the Darlington followers (Q13 and Q14). The delayed video signal at Q14 is fed via its emitter to an AGC comparator Q19 and to the junction of a noise-cancelling amplifier stage (Q16). The noise-cancelled video signal is inverted and amplified by Q16 and then connected to a Darlington emitter-follower output stage (Q57, Q58).

If impulse noise is present on the video signal, Q3 conducts and turns on transistors Q5 and Q12. Q5 inverts and "stretches" the noise pulse width. The output of Q5 is applied to an emitter follower stage (Q12). The signal from Q12, in turn, is applied to the summing junction to the noise-cancelling amplifier Q16. The noise pulse, which has now been amplified, inverted and stretched, is added to the delayed video signal from the emitter of Q14.

Because the video signal has been delayed approximately 300 nanoseconds and the noise pulse has been widened ("stretched") approximately 500 nanoseconds, the output of the combined signal no longer contains impulse noise signals. The derived noise-

gating pulse "surrounds" and effectively eliminates the effects of the impulse noise.

The noise-cancelled video signal, amplified and buffered, is available at Terminal 5 for use in the sync-separator stage. The peak-to-peak amplitude of the noise-cancelled output signal is approximately twice the amplitude of the input video signal at Terminal 8.

Sync Separator (See Figure 3) — The sync separator stage (Q56) clamps the detected sync tips to a fixed reference voltage ($\cong 0.7$ V) across its base-emitter junction, and amplifies a portion of the sync signal to provide dual polarity sync-signal outputs at Terminals 2 (negative) and 3 (positive). The output signals are derived from low-impedance complementary emitter-follower stages; a base current of 100 microamperes into Terminal 4 is sufficient to generate full-amplitude sync signals.

The choice of coupling the noise-cancelled video-signal from the emitter-follower (Terminal 5) to the sync separator (Terminal 4) is a user option. Fig. 4 shows three typical coupling networks.

Fig. 5 illustrates the operation of the AGC circuits. An input ramp signal, simulating the potential to which the AGC filter capacitor may be charged, is applied to Terminal 11. The forward IF AGC output voltage appears at Terminal 13. Under low-signal level conditions (represented by A to B in Fig. 5) the output level is approximately 1.4 volts less than the voltage applied to Terminal 12.

The circuit designer should select the voltage at Terminal 12 to provide the maximum IF gain required for the system. At intermediate signal level conditions (represented by B to C in Fig. 5), the IF AGC signal follows the AGC filter potential. The tuner(s) will operate at maximum gain for good signal-to-noise ratios at these equivalent input signal levels. Point C is a turnover point determined by the open-circuit potential of the tuner-delay bias potentiometer. At this potential, further change in the IF AGC output is inhibited (for good dynamic range) and the tuner AGC potentials are activated (represented by C to D).

The output at Terminal 14 with suitable level shifting is used for tuners requiring reverse AGC, such as MOSFET or electron-tube types. The output at Terminal 15 is used for tuners requiring forward AGC, such as tuners utilizing n-p-n bipolar transistors.

*For additional information refer to the IEEE Transactions on Broadcast and TV Receivers," August 1970, pp. 185-195, Vol. BTR No. 3. Also refer to ICAN6302.

Linear Integrated Circuits

CA3120E, CA3142E

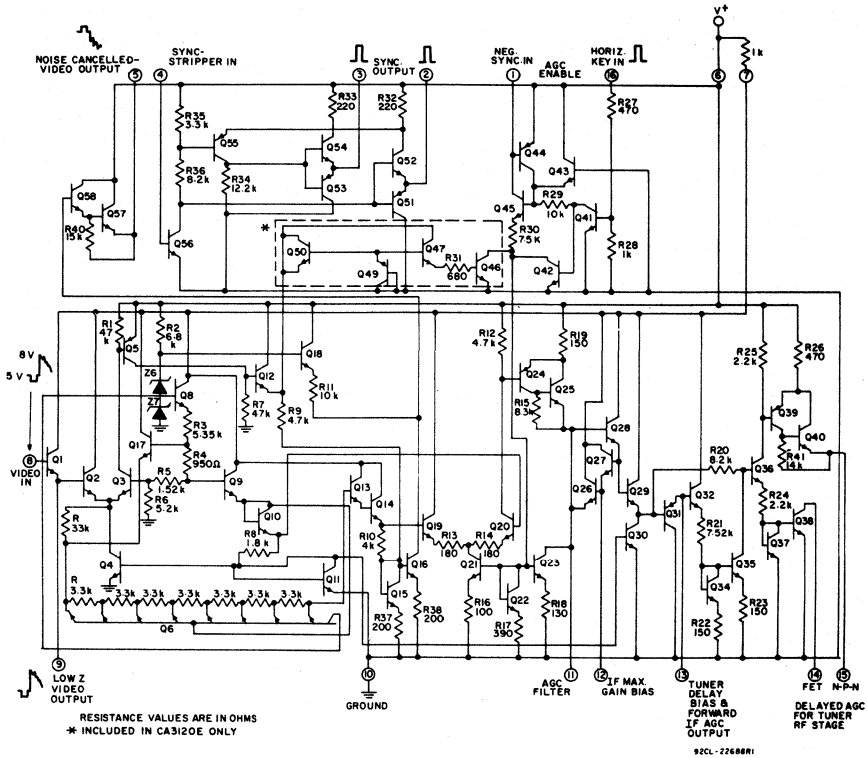
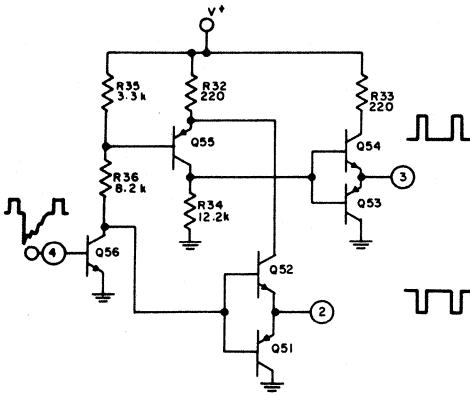


Fig.2 - Schematic diagram of the CA3120E and CA3142E.

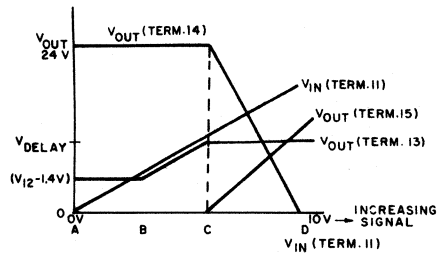
MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

DC SUPPLY VOLTAGE	30 V
DEVICE DISSIPATION:	
Up to $T_A = 55^\circ\text{C}$	750 mW
Above $T_A = 55^\circ\text{C}$	Derate linearly at 7.9 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:	
Operating	-40 to +85 $^\circ\text{C}$
Storage	-65 to +150 $^\circ\text{C}$
LEAD TEMPERATURE (During soldering):	
At a distance not less than 1/32" (0.79 mm)	
from case for 10 seconds max.	+265 $^\circ\text{C}$



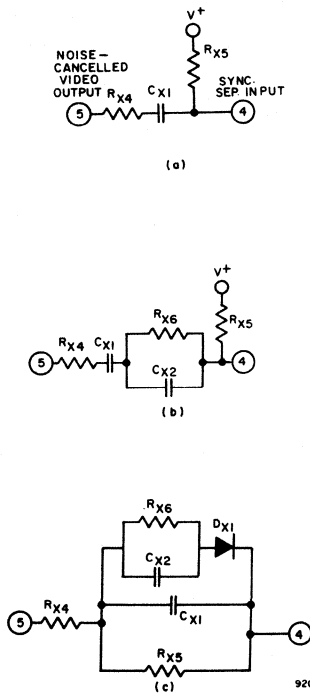
92CS-22644

Fig.3 - Sync separator stage.



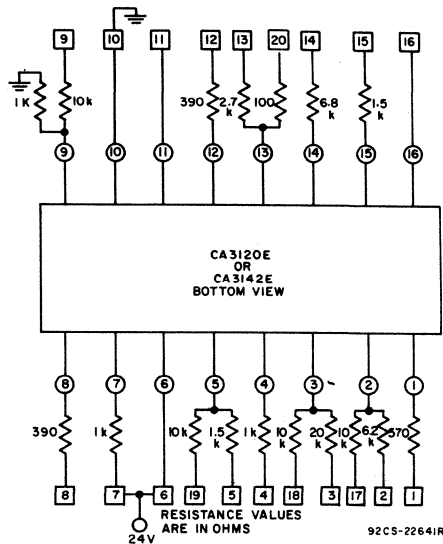
92CS-22646

Fig.5 - Typical operation of the AGC circuits using the CA3120E and CA3142E.



92CS-22645RI

Fig.4 - Typical coupling networks (Term. 5 to Term. 4).



92CS-22641RI

Fig.6 - Test circuit for measuring electrical characteristics of the CA3120E and CA3142E. Refer to Figs. 7 and 8 for switch selector positions.

Linear Integrated Circuits

CA3120E, CA3142E

CHARACTERISTIC	TEST CONDITIONS																			TERMINAL MEASURED
	SWITCH NUMBERS																			
	1	2	3	4	5	8	9	11	12	13	14	15	16	17	18	19	20			
SWITCH POSITION																				
I _{T24}	2	3	1	2	1	2	3	1	1	3	2	1	2	2	2	1	5	2 6 7 9 14		
V _{TH}	2	1	2	1	1	4	3	4	4	3	1	2	2	2	2	1	3	8		
V ₅	2	1	2	1	1	4	3	4	4	3	1	2	2	2	2	2	3	19		
V _{TH(SEP)}	3	1	2	1	1	*	3	3	4	1	1	2	1	2	2	2	1	*		
I _{4(OFF)}	3	1	2	4	2	1	1	1	1	1	1	2	1	2	2	1	1	14		
V _{2L}	1	2	2	3	2	1	1	1	1	1	1	2	1	1	2	1	1	V ₁₇		
V _{2H}	3	3	1	1	2	1	1	1	1	1	1	2	1	1	2	1	1	V ₁₇		
V _{3L}	3	3	1	1	2	1	1	1	1	1	1	2	1	2	1	1	1	V ₁₈		
V _{3H}	3	3	1	3	2	1	1	1	1	1	1	2	1	2	1	1	1	V ₁₈		
I _{11(CH)}	2	1	2	5	2	1	1	5	4	3	1	2	2	2	2	1	5	I ₁₁		
I _{11(DISCH)}	2	1	2	5	1	2	3	6	4	3	1	2	2	2	2	1	5	I ₁₁		
I _{11(LEAK)}	2	1	2	5	2	1	1	6	4	3	2	2	1	2	2	1	5	I ₁₁		
V ₁₁	2	1	2	5	1	2	3	2	3	3	1	2	2	2	2	1	5	V ₁₁		
V ₁₂	3	1	2	5	2	1	1	3	4	3	1	2	1	2	2	1	5	V ₁₂		
V _{13(LOW)}	3	1	2	5	2	2	3	1	1	2	1	2	1	2	2	1	2	V ₁₃		
V _{13(HIGH)}	3	1	2	5	2	2	3	7	4	3	2	1	1	2	2	1	4	V ₂₀		
I _{14(OFF)}	3	1	2	5	2	2	3	3	4	3	3	1	1	2	2	1	5	I ₁₄		
I _{14(ON)}	3	1	2	5	2	2	3	8	4	3	3	1	1	2	2	1	5	I ₁₄		
I _{15(OFF)}	3	1	2	5	2	2	3	3	4	3	2	3	1	2	2	1	5	I ₁₅		
I _{15(ON)}	3	1	2	5	2	2	3	8	4	3	2	3	1	2	2	1	5	I ₁₅		

CAUTION: Remove power before selecting or adjusting switches.

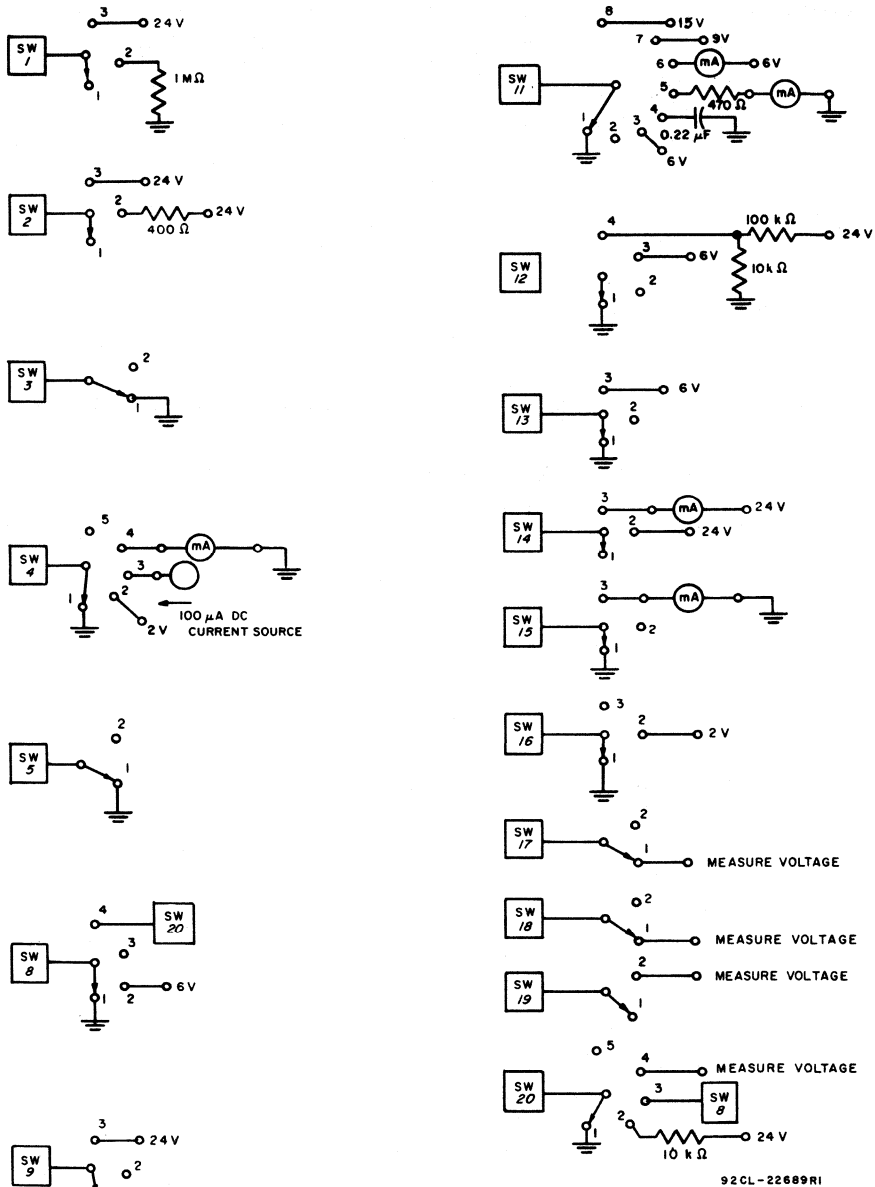
* Reduce voltage at Terminal 8 until V₁₉ decreases. $V_{TH(SEP)} = V_{TH} - V_8$.

NOTE: Switch numbers in italics correspond to numbers in square boxes in Figs. 6 and 8.

Fig. 7 — Test condition values for associated switches 1 through 20 (switches 6, 7, and 10 are omitted). Refer to Figs. 6 and 8 for test circuit and test-condition selector-switch arrangements.

TV/CATV Circuits

CA3120E, CA3142E



92CL-22609R1

NOTE: The italicized numbers in the square boxes refer to the 17 switches (switches 6, 7, and 10 are omitted) of the test circuit and correspond to those given in Figs. 6 and 7.

CAUTION: Remove power before selecting or adjusting switches

Fig.8 — Test condition selector switch arrangement for measuring the electrical characteristics of the CA3120E and CA3142E.

Linear Integrated Circuits

CA3120E, CA3142E

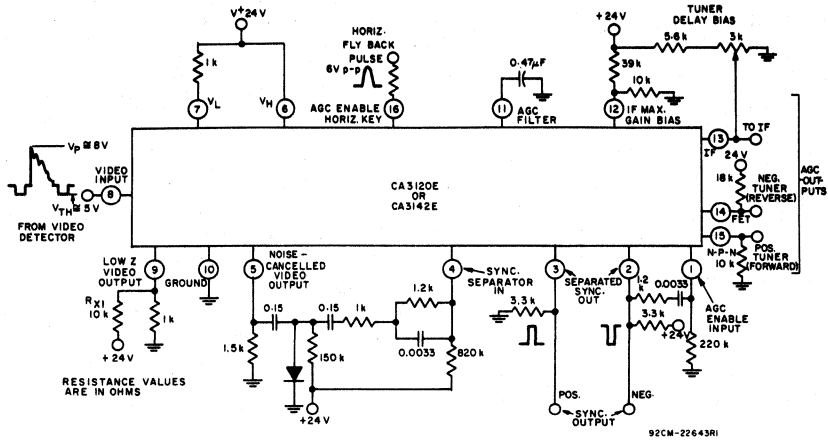
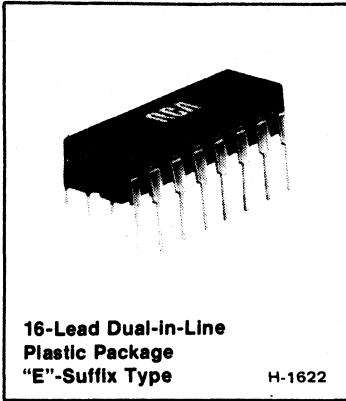


Fig.9 - Typical application using the CA3120E and CA3142E.

TV Luminance Processor



FEATURES:

- Single gain control for luminance and chrominance channels
- 100% dc restoration with "back porch" clamp
- Vertical blanking of both luminance and chrominance channels
- Automatic brightness limiting
- Operates from a 12-V supply
- Silicon-nitride passivated
- Platinum-silicide ohmic contacts

The RCA-CA3135E monolithic silicon integrated circuit operates from a 12-V supply and is used as a low-level luminance processor in TV applications. It performs the function of video and chroma amplification and allows the gain of both channels to be adjusted with a single control voltage. The dc level of "black" is maintained by clamping the level of the "back porch" (back-level reference) of the blanking interval. This clamping feature provides for 100%

dc restoration. Vertical blanking is applied to the luminance as well as to the chrominance channel so that vertical interval test signals (VITS) interference is eliminated. Automatic brightness limiting (ABL) is accomplished by gain reduction in the luminance and chrominance channels while maintaining black level.

The CA3135E is supplied in the 16-lead dual-in-line plastic package (E suffix).

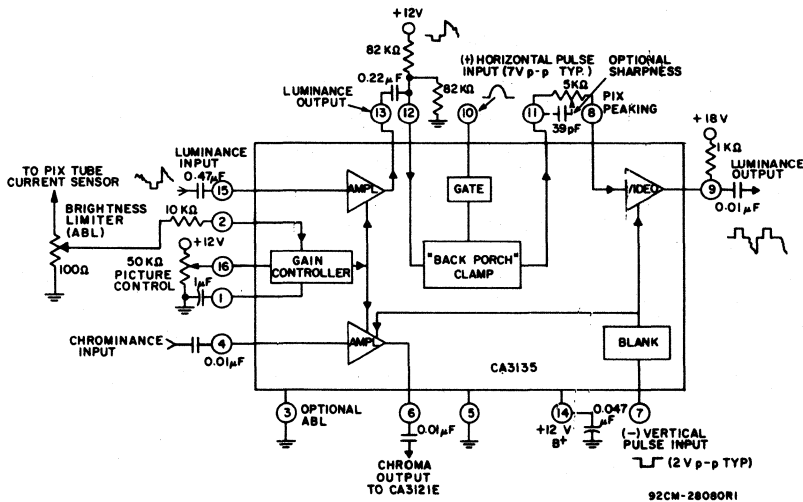
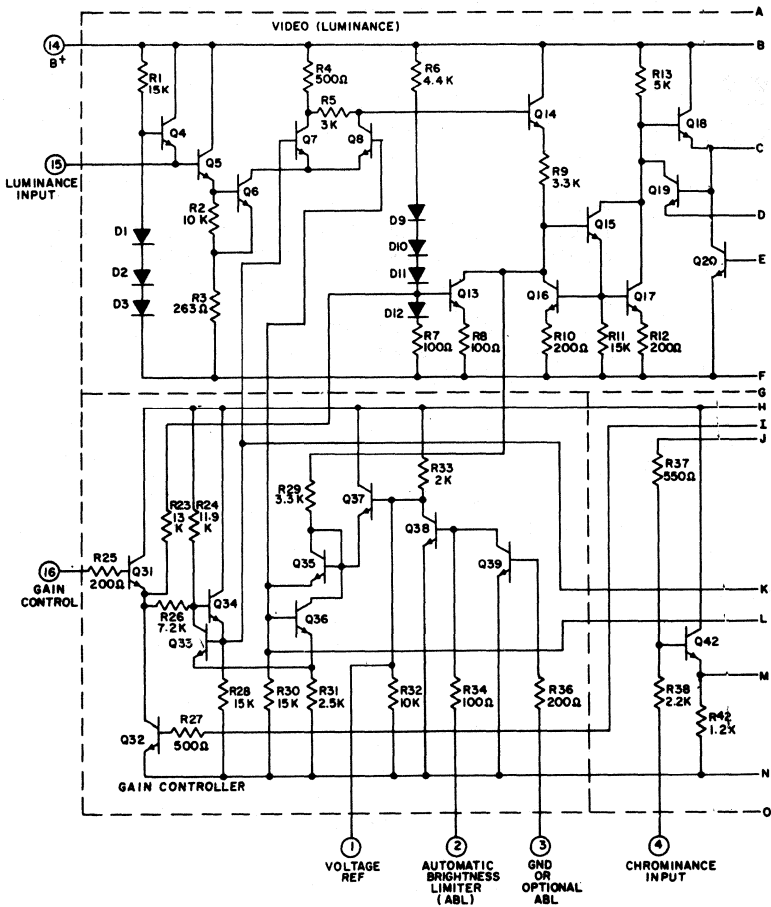


Fig. 1 - Block diagram.

Linear Integrated Circuits

CA3135E



92CL-28079R2

Fig. 2 - Schematic diagram (cont'd on next page).

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE:

At terminal 9	28 V
At terminal 14	15 V

DC SUPPLY CURRENT:

At terminal 9	30 mA
At terminal 14	50 mA

DEVICE DISSIPATION:

Up to $T_A = 55^\circ\text{C}$	750 mW
Above $T_A = 55^\circ\text{C}$	Derate linearly at $7.9\text{ mW}/^\circ\text{C}$

AMBIENT TEMPERATURE RANGE:

Operating	-40 to $+85^\circ\text{C}$
Storage	-65 to $+150^\circ\text{C}$

LEAD TEMPERATURE (During Soldering):

At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10 seconds max.	$+265^\circ\text{C}$
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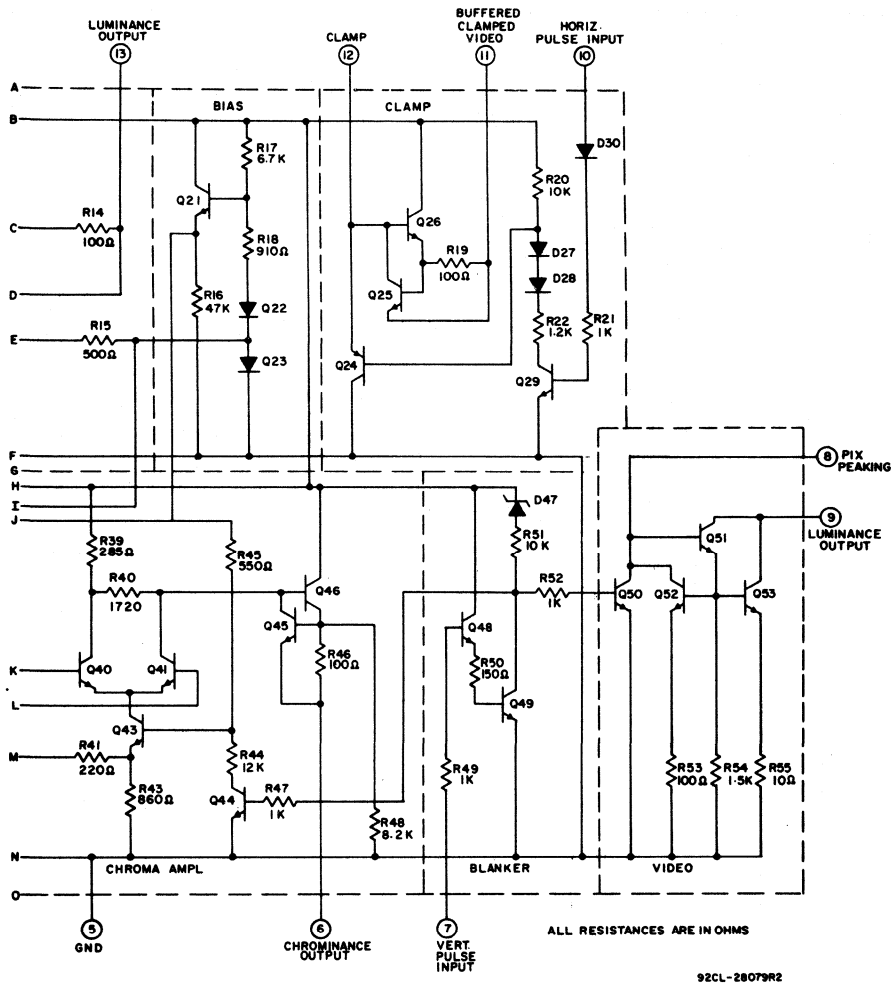
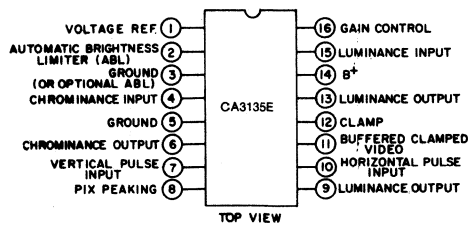


Fig. 2 - Schematic diagram (cont'd from previous page).



92CS-28081

Terminal Assignment

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$ (See Fig. 4)

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
Min. Video Gain	S1, S2 = 1; S3, S4 = 2 $V_{IN} = 70\text{ mV}_{RMS}$, $f = 100\text{ kHz}$, $V_{16} = 12\text{ V}$	0.2	0.35	0.5	V_{RMS}
Max. Video Gain	S2 = 1; S1, S3, S4 = 2 $V_{IN} = 70\text{ mV}_{RMS}$, $f = 100\text{ kHz}$, $V_{16} = 0\text{ V}$	1.6	2.1	2.6	V_{RMS}
Limited Video Gain	S2, S4 = 1, S1, S3 = 2 $V_{IN} = 70\text{ mV}_{RMS}$, $f = 100\text{ kHz}$, $V_{16} = 0\text{ V}$	—	0.3	—	V_{RMS}
Min. Chroma Gain	S1, S3 = 1; S2, S4 = 2; $V_{16} = 12\text{ V}$; chroma in = 530 mV_{RMS} , $f = 3.58\text{ MHz}$	—	0.095	—	V_{RMS}
Max. Chroma Gain	S3 = 1; S2 = 2, $V_{16} = 0\text{ V}$; chroma in; S1 = 2, S4 = 2 530 mV_{RMS} , $f = 3.58\text{ MHz}$	0.5	0.65	0.8	V_{RMS}
Video Freq. Response	S2 = 1, S1, S3, S4 = 2 $V_{IN} = 70\text{ mV}_{RMS}$; $V_{16} = 0\text{ V}$; $f = 3.58\text{ MHz}$	1	1.9	2.8	V_{RMS}
Chroma Phase Angle	S3 = 1; S2 = 2; $V_{16} = 0\text{ V}$; chroma in; S1 = 2, S4 = 2 530 mV_{RMS} , $f = 3.58\text{ MHz}$	12	19.5	27	Degrees
Chroma Gain with V^+ Variation	Vary V^+ from 10.8 V (REF.) to 13.2 V $V_{16} = 50\%$ of V^+ ; S1, S3 = 1 S2, S4 = 2	—	1.5	—	dB
Video Gain with V^+ Variation	Vary V^+ from 10.8 V (REF.) to 13.2 V $V_{16} = 50\%$ of V^+ ; S1, S2 = 1 S3, S4 = 2	—	1.5	—	dB

Typical max. luminance input before clipping ($f = 100\text{ kHz}$):

V_{16}	INPUT
+12 V	2.5 V_{p-p}
+6 V	0.75 V_{p-p}
0 V	0.45 V_{p-p}

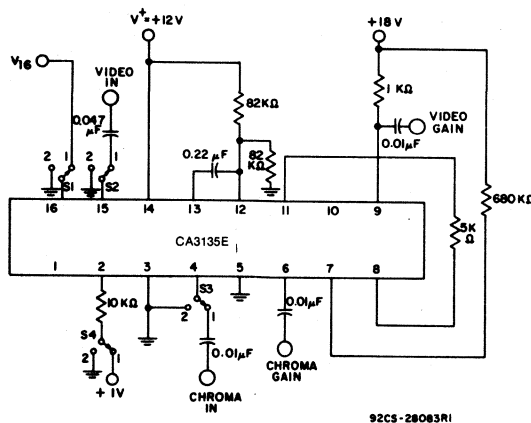


Fig. 4 — Dynamic characteristics test circuit.

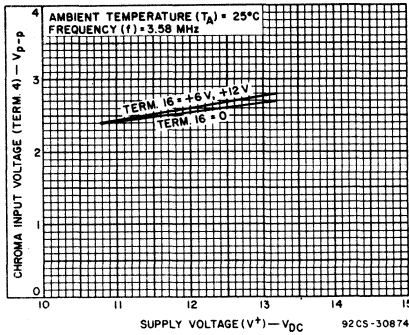


Fig. 5 - Typical chroma amplifier maximum linear voltage as a function of supply voltage.

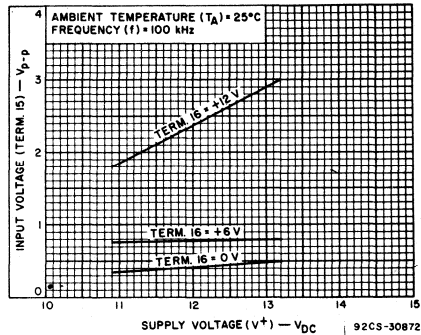


Fig. 6 - Typical maximum linear luminance voltage at terminal 15 as a function of supply voltage.

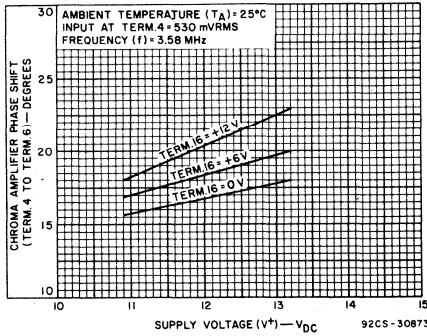


Fig. 7 - Typical chroma amplifier phase shift as a function of supply voltage.

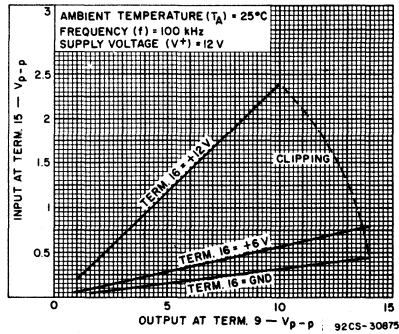


Fig. 8 - Input voltage as a function of output voltage.

CIRCUIT DESCRIPTION

(See fig. 2 for schematic diagram).

A video (luminance) signal from the receiver's "second detector" is coupled through a capacitor to term. 15 with sync-negative polarity. For purposes of the following amplifier, the level is clamped at the most negative point (sync tips) at the input (this is not the point at which the final "black"-level clamping, or dc restoration, is performed). The capacitor at term. 15 is charged on the most negative excursions of the signal by conduction of Q4. Positive signal excursions lift the emitter of Q4 into cutoff. The signal voltage on R3 develops a signal current in Q6. The current passes through Q7 and Q8, the division of current depends on the condition of the gain-adjusted signal voltage on the load resistors (discussed below). The gain-adjusted signal voltage on the load resistors is converted to current by the emitter-follower Q14 into R9, and fed into the current mirror, Q15, Q16, and Q17. The output of the current mirror develops a voltage across R13. The dc level is shifted by withdrawing some current from the input to the mirror. The fixed dc-level shifting current is developed in R6 and its diode string and is mirrored in Q13. Because the dc level is altered by adjustment of the gain, compensating dc currents that depend on these adjustments are fed into the mirrors through

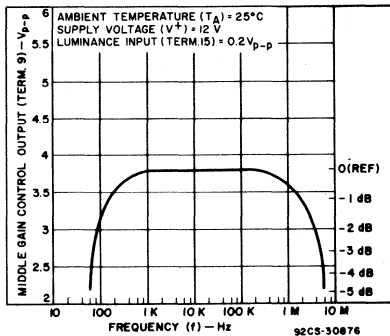


Fig. 9 - Typical gain-bandwidth response.

R13 and R29. The compensations are arranged so that, as gain is varied, the dc level of "black" is approximately constant at the output term. 13. The output is driven by emitter follower Q18, which has a short-circuit pulldown protection circuit, R14 and Q19. A constant-current source Q20 loads the emitter-follower to prevent distortion in the emitter-follower that may result from using a resistive load. The constant current is derived by mirroring the current in the diode D23. The resistor R15 prevents serious interaction with another current source mirrored from this point in case Q20 saturates.

The video output signal at term. 13 is coupled by a capacitor to term. 12. The polarity has not been inverted by the first amplifier, and sync is in the negative direction at this point. Black-level clamping is accomplished by application of a flyback pulse to term. 10. Between pulse peaks, Q29 is not conducting, and the base of Q24 goes up to the supply voltage so that term. 12 can be at any voltage between ground and the supply. While the flyback pulse is positive, that is during the blanking interval, the base of Q24 is held at about 2.8 volts. The most positive signal excursion during that time will cause Q24 to conduct with the result that the capacitor feeding term. 12 is charged until the most positive point of the signal is just at the conduction point, about 3.5 volts. The most positive part of the signal *during blanking* is the "back porch" or black-level reference. During trace time, the signal swings more positive, but the dc level of black is preserved regardless of the levels of sync or video signals. Term. 12 is a high-impedance point, and the emitter-follower Q26 is used to bring the signal out to term. 11.

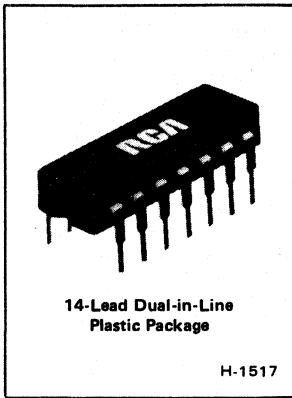
The signal voltage at term. 11 is directly coupled through a resistor to term. 8, generating a current in term. 8. This current is amplified 10 times by the current mirror Q51, Q52, and Q53. Blanking during the vertical retrace interval is accomplished at Q50 via term. 7. Term. 7 is normally high enough to keep Q49 in saturation. A negative pulse from the vertical circuit cuts Q49 off, allowing some of the current through R51 to saturate Q50. When Q50 sinks the term. 8 input current, there is no output from term. 9 — as if the signal were blacker-than-black. The output current from term. 9 is used to drive the receiver's RGB matrix and the amplifiers that drive the picture tube.

The chrominance signal is taken from the first chroma amplifier following the auto-

matic chroma control (ACC) and coupled through a capacitor to term. 4. The signal is attenuated by R38 and R37 and applied to an emitter-follower amplifier which drives the emitter of Q43. The current is steered through Q40 and Q41 depending on the gain-control conditions to the load resistors. An emitter-follower Q46 feeds term. 6, and R46 and Q45 provide short-circuit protection. The chroma amplifier is also blanked via the input at term. 7. The negative pulse at term. 7 allows the current through R51 to feed the base of Q44 (as well as the base of the video blanker, Q50). When Q44 saturates, the current is cut off in Q43 to disable the amplifier.

The combined gain control for the video and chroma sections is operated by varying the voltage on term. 16 between ground and the positive supply. Term. 16 has an emitter-follower Q31 loaded by a current source Q32. The voltage on term. 16 then determines whether the flow of current in R31 goes through Q36 or through Q33 to the resistors R24 and R26. The current on the Q33 side, a portion of the total current, is varied linearly by the control voltage. The gain-control amplifiers are slaves which follow the linear current control. The transistors Q34 and Q35 are driven as Darlington stages to reduce base-current effects in the control circuit. The normal gain-control function causes a change in the voltage on the base of Q34 with respect to the reference voltage at the base of Q35. The gain can also be changed by altering this reference voltage. This change in reference voltage is also used for "brightness limiting". The picture-tube current is sensed, and, when it exceeds some predetermined level, a voltage applied to term. 2 turns Q38 ON to reduce the reference voltage, thereby reducing the gain. Under these conditions, there is a closed feedback loop; the gain is set at a point such that the picture-tube current is just sufficient to cause a little conduction in Q38.

CA3143E



TV Luminance Processor

Features:

- Black-level clamping
- Linear dc controls for brightness, contrast, and peaking
- Horizontal and vertical blanking
- Operates with standard or tapped delay line

The CA3143E is a monolithic silicon integrated circuit that performs the luminance processing functions of amplification; contrast, brightness and peaking control; blanking; and black-level clamping. This device, when used in conjunction with

the CA3126Q chroma processor and the CA3137E chroma demodulator, will provide a luminance/chrominance system having excellent tracking of controls. The CA3143E is supplied in a 14-lead dual-in-line plastic package.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY CURRENT (Into Terminal 13)*	59.5 mA
DEVICE DISSIPATION:*	
Up to $T_A = 55^\circ\text{C}$	750 mW
Above $T_A = 55^\circ\text{C}$	derate linearly 7.9 mW/ $^\circ\text{C}$
AMBIENT-TEMPERATURE RANGE:	
Operating	-40 to +85 $^\circ\text{C}$
Storage	-65 to +150 $^\circ\text{C}$
LEAD TEMPERATURE (During soldering):	
At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10 s max.	+265 $^\circ\text{C}$

* Although the CA3143E is rated for maximum dissipation of 750 mW, it is recommended that the current into terminal 13 be limited

by external circuit resistance to 39 mA for a typical voltage at terminal 13 of 11.8 volts.

ELECTRICAL CHARACTERISTICS at T_A = 25°C

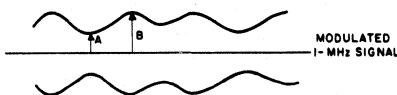
Characteristic	Bias Volts (V)	Test Conditions											LIMITS			UNIT
		Switch Numbers											Min.	Typ.	Max.	
		S1	S2	S3	S4	S5	S6	S7	S8	S9	S10	S11				
Switch Positions For Characteristics Measurements																
STATIC																
Voltage: At Term. 13 (V13)	6.1	2	1	1	2	2	4	1	2	2	1	1	11	11.8	13.2	V
Quiescent Voltage At Term. 4 (V4)	6.1	2	1	1	2	2	3	1	2	2	1	1	3.3	4	5.7	V
Quiescent Voltage At Term. 7 (V7)	6.1	2	1	1	2	2	2	1	2	2	1	1	7.1	7.7	8.3	V
Current into Term.13 (Term.13 Connected to +11 V) (I13)	6.1	2	1	1	2	2	3	1	2	2	1	2	10	19	30	mA
DYNAMIC																
Wide-Band Gain (Note 1)	5.8	1	1	1	2	1	2	1	1	1	2	1	6	8.3	11	dB
Contrast Gain Reduction (Note 2)	5.8	1	1	1	2	1	2	1	1	2	2	1	27	30	—	dB
Peaking Gain (Note 1)	5.8	1	1	2	2	1	2	1	1	1	2	1	15	18.4	22	dB
Peaking Gain Reduction (Note 3)	5.8	1	1	2	2	1	2	1	1	1	2	1	16	18	—	dB
Max. Intermodulation Distortion: 2V (Note 4)	5.8	1	—	1	1	1	2	—	2	1	2	1	—	20	—	%
3V (Note 5)	5.8	1	—	1	1	1	2	—	2	1	2	1	—	40	—	%

Note 1: Set 50-kHz generator for 100 mVp-p. Adjust R1 Peaking Control (See Fig.2) for minimum setting. Measure wide-band gain at terminal 7.

Note 2: Set 50-kHz generator for 100 mVp-p. Adjust R1 for minimum setting. Measure contrast gain reduction at terminal 7.

Note 3: Set 50-kHz generator for 100 mVp-p. Adjust R1 for maximum setting. Measure peaking gain reduction at terminal 7.

Note 4: Adjust R1 for minimum setting. With S2 at switch position 1 and S7 at switch position 3, set 50-kHz generator for 2 Vp-p. Then with S2 at switch position 2, set 1 MHz generator for 100 mVp-p. Then with S7 at switch position 2, measure downward modulation of the 1-MHz signal due to the 50-kHz signal.



A = Amplitude of 50 kHz signal at deepest trough

B = Peak amplitude of 50 kHz signal

$$\text{Downward Modulation} = \frac{B-A}{B}$$

92CS-27422

Note 5: Repeat step 4 except that the 50-kHz generator must be set at 3 Vp-p.

Linear Integrated Circuits

CA3143E

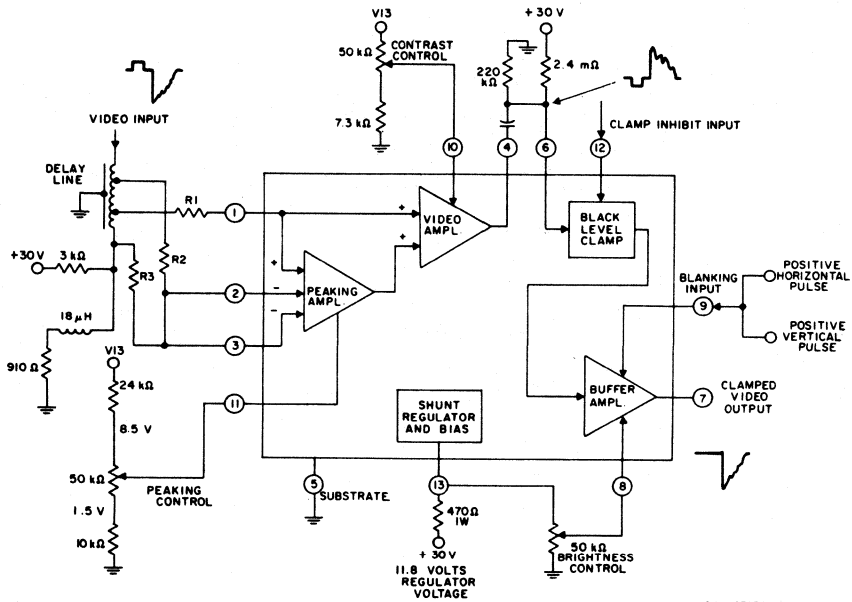
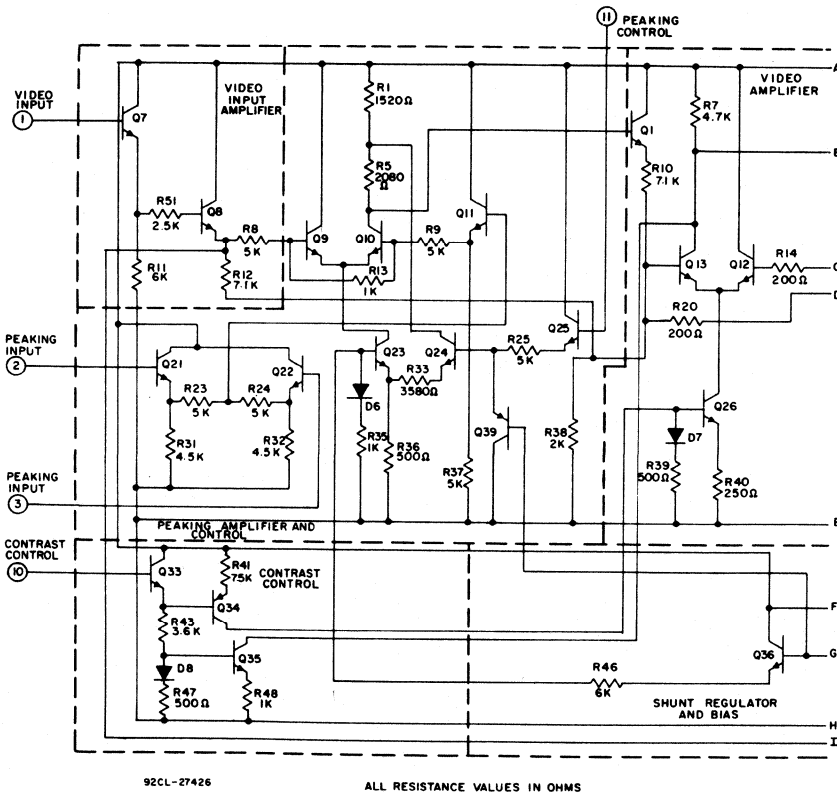


Fig. 1 - Functional block diagram.



92CL-27426

ALL RESISTANCE VALUES IN OHMS

Fig. 3 - Schematic diagram of CA3143E (cont'd on next page).

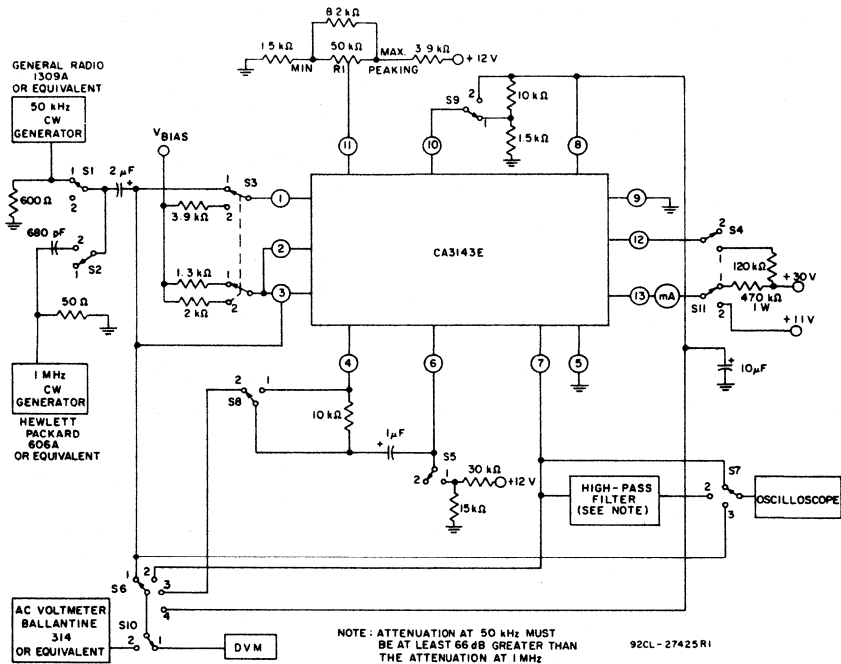


Fig. 2 - Test circuit.

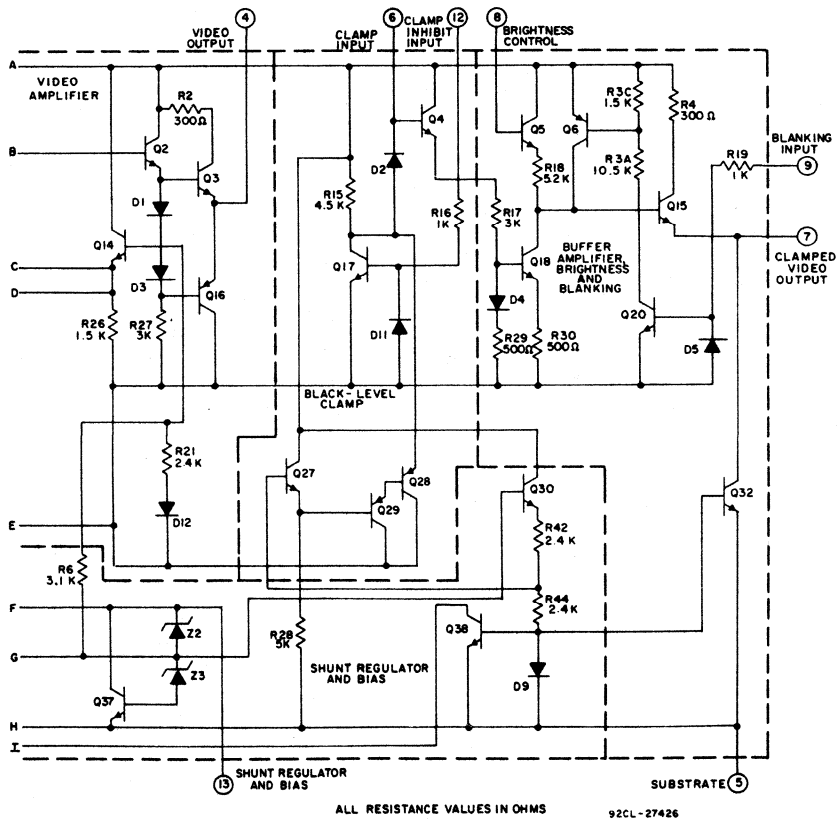


Fig. 3 - Schematic diagram of CA3143E (cont'd from preceded page).

CIRCUIT DESCRIPTION

Fig. 1 is a block diagram of the CA3143E indicating the internal functions as well as external circuitry and signals. The video input signal with positive-going sync is applied to the input of the tapped delay line. Signals from fixed taps of the delay line are applied to terminals 1, 2 and 3 of the CA3143E. In referring to Fig.4, the signal from the delay line tap A is applied to the video input at terminal 1. The signals from

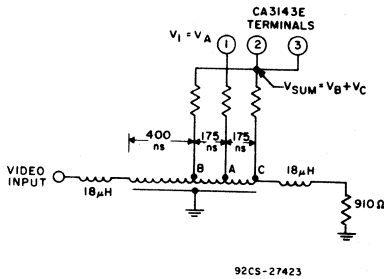


Fig.4 - Tapped delay line.

taps B and C are summed where $V_A + V_B = V_{sum}$. The signal (V_{sum}) is then applied to the parallel connection of the peaking input terminals, 2 and 3. The video input signal is applied to a non-inverting input of the peaking amplifier while the peaking input signal (V_{sum}) is applied to an inverting input of the peaking amplifier.

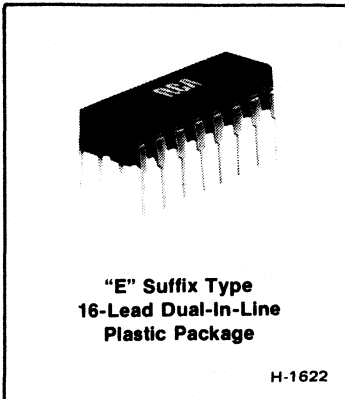
Low-frequency video components are unattenuated, while high-frequency components are attenuated as a function of the delay-line tap points. The peaking amplifier is a differential amplifier, so that the output is proportional to V_1 minus V_{sum} . At low frequencies, the signal at terminals 2 and 3 is unattenuated, and the peaking amplifier produces no output at these frequencies. However, at high frequencies the signal at terminals 2 and 3 is attenuated thus, the

peaking amplifier output consists of high-frequency video. The peaking control setting determines the amplitude of the peaking signal which is then fed to the video amplifier, where it is added to the video input signal and amplified. The setting of the peaking control does not substantially affect the dc quiescent voltage at terminal 4.

The low-impedance video amplifier output is at terminal 4. The signal is fed through an external coupling capacitor to terminal 6, the black-level clamp input. The action of the black-level clamp is such that it clamps to the black level rather than to the sync level. Refer to the circuit diagram in Fig.3. Consider the situation where no signal is applied to terminal 12. Terminal 6 is biased through diode D2. The signal at terminal 6 will clamp its most negative excursion (sync pulse) to the anode voltage of D2. However, if a positive pulse is applied to terminal 12 during the sync interval, the anode of D2 is forced to ground due to saturation of Q17. The clamp is thus disabled, and terminal 6 will clamp to the next lower signal level, the black level.

The clamped video signal at terminal 6 is amplified and inverted at terminal 7. Blanking is accomplished by applying horizontal and vertical sync pulses to terminal 9. The pulses turn ON p-n-p transistor Q6 which shorts the base of transistor Q15 to the terminal 13 supply voltage. The brightness control function is accomplished by varying the voltage on terminal 8. The gain of the inverter stage remains constant, but the dc reference voltage follows the terminal 8 voltage. The contrast control function is accomplished by varying the voltage of terminal 10. Increasing the voltage on terminal 10 lowers the gain of the video amplifier. This reduction in gain does not substantially affect the dc quiescent voltage at terminal 4.

TV Luminance Processor



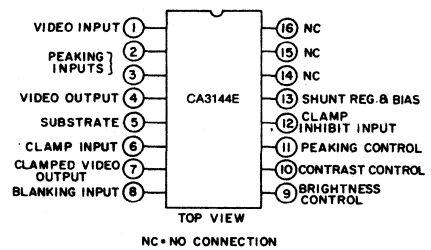
FEATURES:

- Black-level clamping
- Linear dc controls for brightness, contrast, and peaking
- Horizontal and vertical blanking
- "Hermetic Chip" construction
- Silicon nitride passivated
- Platinum silicide ohmic contacts
- Operates with standard or tapped delay line

The CA3144E is a monolithic silicon integrated circuit that performs the luminance processing functions of amplification; contrast, brightness and peaking control; blanking; and black-level clamping.

This device, when used in conjunction with the CA3126Q chroma processor and the CA3137E chroma demodulator, will provide a luminance/chrominance system having excellent tracking of controls. The CA3144E is supplied in a 16-lead dual-in-line plastic package ("E" suffix).

TERMINAL ASSIGNMENT



92CS-28107

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY CURRENT (Into Terminal 13)*	57 mA
DEVICE DISSIPATION:*	
Up to $T_A = 55^\circ\text{C}$	750 mW
Above $T_A = 55^\circ\text{C}$	derate linearly 7.9 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:	
Operating	-40 to +85 $^\circ\text{C}$
Storage	-65 to +150 $^\circ\text{C}$
LEAD TEMPERATURE (During soldering):	
At distance 1/16 \pm 1/32 inch (1.59 \pm 0.79 mm)	
from case for 10 s max.	+265 $^\circ\text{C}$

*Although the CA3144E is rated for maximum dissipation of 750 mW, it is recommended that the current into terminal 13 be limited by external circuit resistance to 39 mA for a typical voltage at terminal 13 of 12.3 volts.

CA3144E

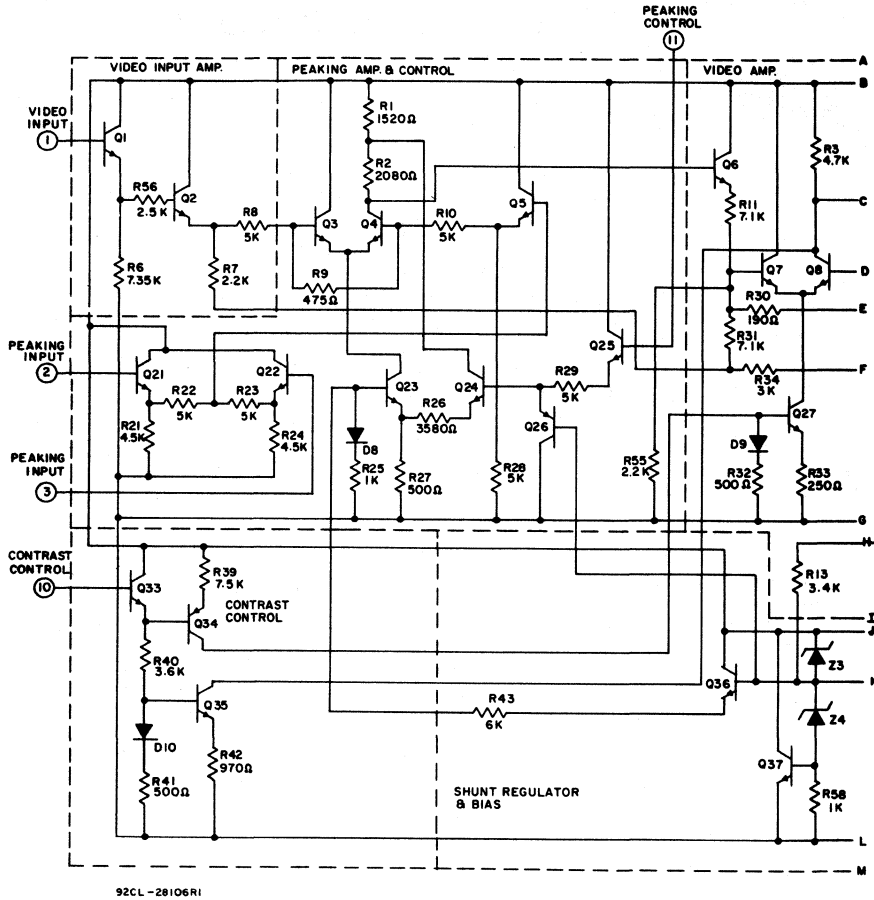


Fig. 1 - Schematic diagram (cont'd on next page).

CIRCUIT DESCRIPTION

Fig. 1 is a block diagram of the CA3144E indicating the internal functions as well as external circuitry and signals. The video input signal with negative-going sync is applied to the input of the tapped delay line. Signals from fixed taps of the delay line are applied to terminals 1, 2, and 3 of the CA-

3144E. In referring to Fig. 2, the signal from the delay line tap A is applied to the video input at terminal 1. The signals from taps B and C are summed where $V_A + V_B = V_{SUM}$. The signal (V_{SUM}) is then applied to the parallel connection of the peaking input terminals, 2 and 3. The video input signal is applied to a non-inverting input of the peaking amplifier while the peaking input signal (V_{SUM}) is applied to an inverting input of the peaking amplifier.

Low-frequency video components are un-attenuated, while high-frequency components are attenuated as a function of the delay-line tap points. The peaking amplifier is a differential amplifier, so that the output is proportional to V_1 minus V_{SUM} . At low frequencies, the signal at terminals 2 and 3 is unattenuated, and the peaking amplifier produces no output at these frequencies. However, at high frequencies the signal at ter-

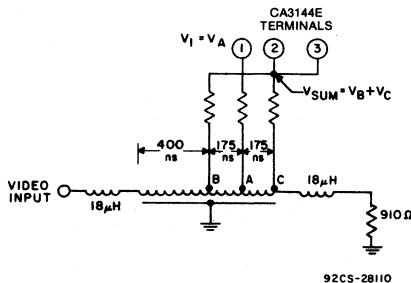


Fig. 2 - Tapped delay line.

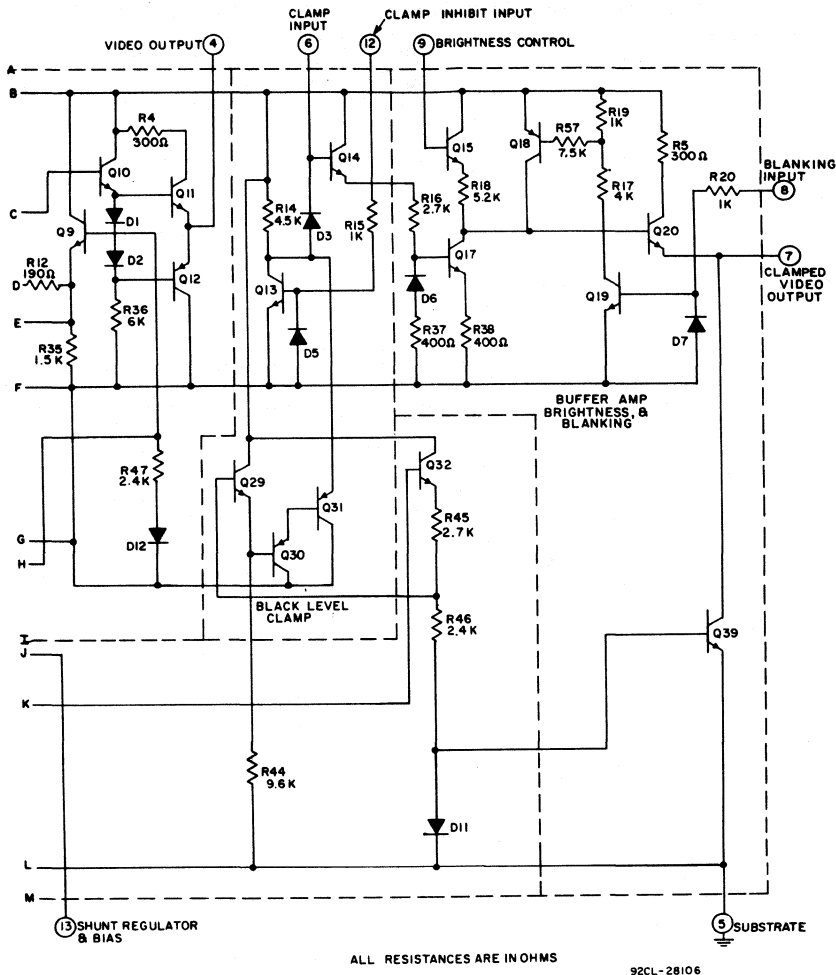


Fig. 1 - Schematic diagram (cont'd from previous page).

minals 2 and 3 is attenuated thus, the peaking amplifier output consists of high-frequency video. The peaking control setting determines the amplitude of the peaking signal which is then fed to the video amplifier, where it is added to the video input signal and amplified. The setting of the peaking control does not substantially affect the dc quiescent voltage at terminal 4.

The low-impedance video amplifier output is at terminal 4. The signal is fed through an external coupling capacitor to terminal 6, the black-level clamp input. The action of the black-level clamp is such that it clamps to the black level rather than to the sync level. Refer to the circuit diagram in Fig. 1. Consider the situation where no signal is applied to terminal 12. Terminal 6 is biased through diode D3. The signal at terminal 6 will clamp its most negative excursion (sync pulse) to the anode voltage of D3. However, if a positive pulse is applied to terminal 12

during the sync interval, the anode of D3 is forced to ground due to saturation of Q13. The clamp is thus disabled, and terminal 6 will clamp to the next lower signal level, the black level.

The clamped video signal at terminal 6 is amplified and inverted at terminal 7. Blanking is accomplished by applying horizontal and vertical sync pulses to terminal 8. The pulses turn ON p-n-p transistor Q18 which shorts the base of transistor Q20 to the terminal 13 supply voltage. The brightness control function is accomplished by varying the voltage on terminal 9. The gain of the inverter stage remains constant, but the dc reference voltage follows the terminal 8 voltage. The contrast control function is accomplished by varying the voltage of terminal 10. Increasing the voltage on terminal 10 lowers the gain of the video amplifier. This reduction in gain does not substantially affect the dc quiescent voltage at terminal 4.

Linear Integrated Circuits

CA3144E

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

Characteristic	Bias Volts (V)	Test Conditions											LIMITS			U N I T S
		Switch Numbers											Min.	Typ.	Max.	
		S1	S2	S3	S4	S5	S6	S7	S8	S9	S10	S11				
Switch Positions For Characteristics Measurements																
STATIC																
Voltage: At Term. 13 (V13)	6.5	2	1	1	2	2	4	1	2	2	1	1	11	12.3	13.2	V
Quiescent Voltage At Term. 4 (V4)	6.5	2	1	1	2	2	3	1	2	2	1	1	3.3	4	5.7	V
Quiescent Voltage At Term. 7 (V7)	6.5	2	1	1	2	2	2	1	2	2	1	1	7.1	7.7	8.3	V
Current into Term.13 (Term.13 Connected to +11 V) (I13)	6.5	2	1	1	2	2	3	1	2	2	1	2	10	18	30	mA
DYNAMIC																
Wide-Band Gain (Note 1)	7.3	1	1	1	2	1	2	1	1	1	2	1	1	3	5	dB
Contrast Gain Reduction (Note 2)	7.3	1	1	1	2	1	2	1	1	2	2	1	27	30	-	dB
Peaking Gain (Note 1)	7.3	1	1	2	2	1	2	1	1	1	2	1	9	13	17	dB
Peaking Gain Reduction (Note 3)	7.3	1	1	2	2	1	2	1	1	1	2	1	16	18	-	dB
Max. Intermodulation Distortion: 3.8 V (Note 4)	7.3	1	-	1	1	1	2	-	2	1	2	1	-	20	-	%
5 V (Note 5)	7.3	1	-	1	1	1	2	-	2	1	2	1	-	40	-	%

Note 1:

Set 50-kHz generator for 200 mV_{rms}. Adjust R1 peaking control for minimum setting (see Fig. 2).

Measure wide-band gain at terminal 7.

Note 2:

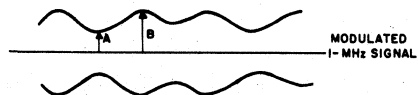
Set 50-kHz generator for 200 mV_{rms}. Adjust R1 for minimum setting. Measure contrast gain reduction at terminal 7.

Note 3:

Set 50-kHz generator for 200 mV_{rms}. Adjust R1 for maximum setting. Measure peaking gain reduction at terminal 7.

Note 4:

Adjust R1 for minimum setting. With S2 at switch position 1 and S7 at switch position 3, set 50-kHz generator for 3.8 V_{p-p}. Then with S2 at switch position 2, set 1-MHz generator for 200 mV_{rms}. Then with S7 at switch position 2, measure downward modulation of the 1-MHz signal due to the 50-kHz signal.



A = Amplitude of 50-kHz signal at deepest trough
B = Peak amplitude of 50-kHz signal

$$\text{Downward Modulation} = \frac{B-A}{B}$$

92CS-27422

Note 5:

Repeat step 4 except that the 50-kHz generator must be set at 5 V_{p-p}.

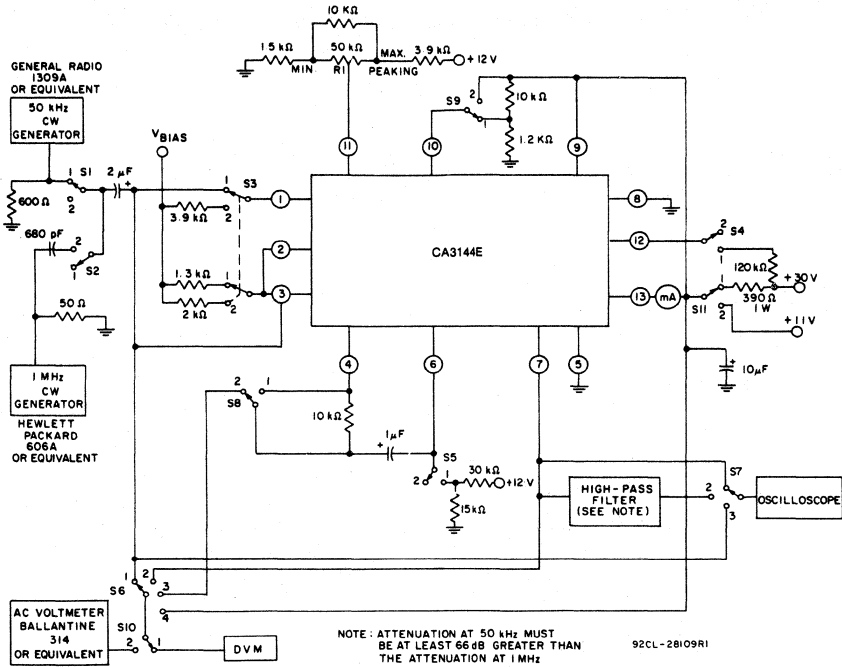


Fig. 3 - Test circuit.

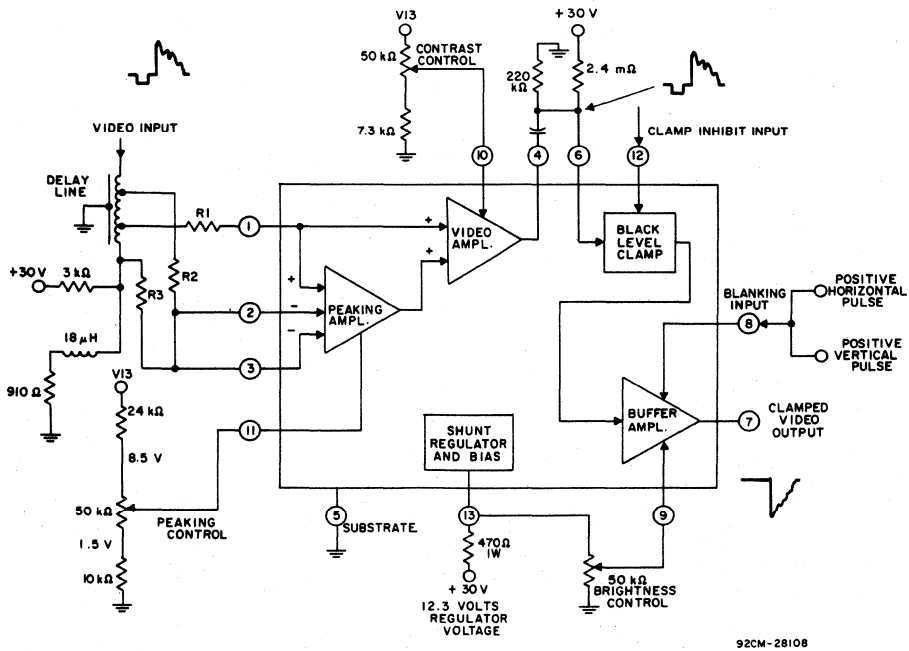
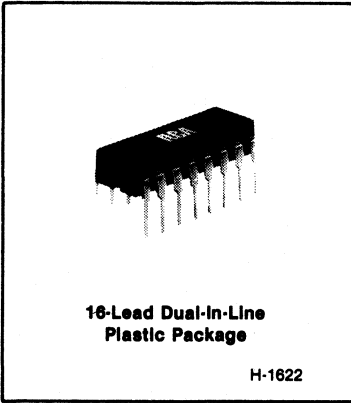


Fig. 4 - Functional block diagram.

CA3156E



Video/Chroma Processor

Features:

- Automatic black-level control
- Automatic controls for contrast and peaking
- Automatic color-level control
- Horizontal and vertical blanking
- Automatic beam-current limiting
- Positive or negative vertical blanking pulses
- Internal noise protection for automatic functions

The RCA-CA3156E is a monolithic silicon integrated circuit that performs the luminance processing functions in color TV receivers. This circuit amplifies chroma signals, provides horizontal and vertical blanking, and automatically controls contrast, brightness, peaking, and black and chroma levels.

The CA3156E is well-suited for color TV receiver applications which use the CA3159E horizontal processor, the CA3216Q chroma processor, and the CA3172E color demodulator.

The CA3156E is supplied in a 16-lead dual-in-line plastic package.

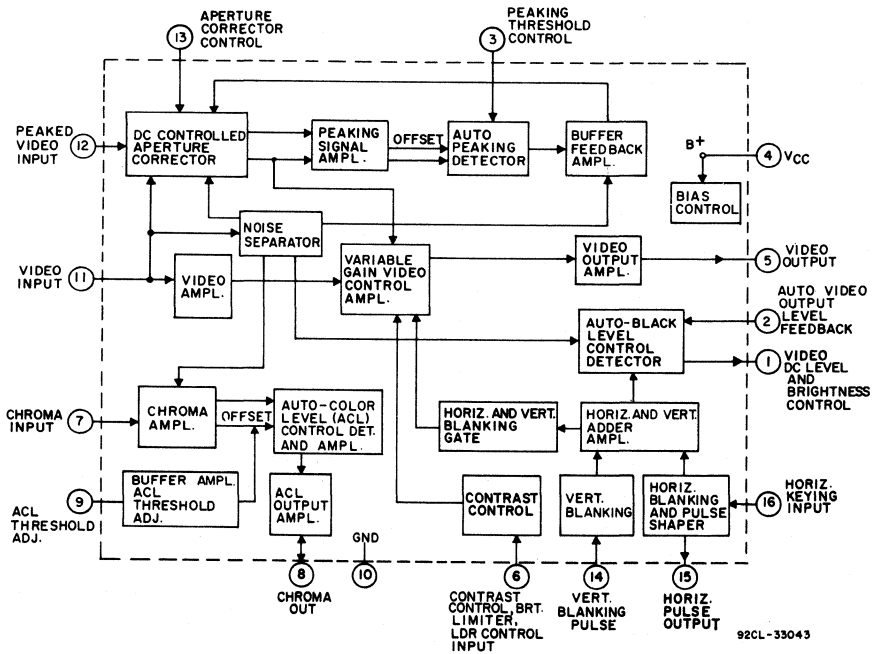


Fig. 1 — Block diagram of CA3156E.

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$ and $V^+ = 24\text{ V}$ and Referenced to Test Circuit (See Fig. 3)

CHARACTERISTIC	TEST CONDITION	LIMITS			UNITS
		Min.	Typ.	Max.	
<i>Static Characteristics</i>					
Total Supply Current		13	16.0	19	mA
Reference Bias Level Pin 7			5.25		V
Reference Level Pin 2 $S_2 = 2$ (with 1 mA into Pin 1) $S_3 = 2$			12.2		V
<i>Dynamic Characteristics</i>					
Max. Video Gain—Read e_o	$e_{in} = 1\text{ V}_{p-p}$ $f = 100\text{ kHz}$ S_5 to Pos. 1		13.5		dB
Min. Video Gain—Read e_o	$e_{in} = 1\text{ V}_{p-p}$ $f = 100\text{ kHz}$ S_5 to Pos. 2		-4.4		dB
Relative Freq. Response—Read e_o	$e_{in} = 1\text{ V}_{p-p}$ $f = 3.58\text{ MHz}$ S_5 to Pos. 1		-0.2		dB
Contrast Gain Reduction—Read e_o	$e_{in} = 1\text{ V}_{p-p}$ $f = 100\text{ kHz}$ S_5 Pos. 1 to Pos. 2		-17.9		dB
Auto-Peaking Level—Read P_3 to P_{13}	$e_{in} = 1\text{ V}_{p-p}$ S_5 to Pos. 1		165		mV
Auto-Peaking Level—Read P_3 to P_{13}	$e_{in} = 0.5\text{ V}_{p-p}$ S_5 to Pos. 1		115		mV
Auto-Peaking Level—Read P_3 to P_{13}	$e_{in} = 0\text{ V}_{p-p}$ S_5 to Pos. 1		0		mV
Max. Chroma Out Level—Read P_8 $E_5 = 5\text{ V dc}$	$e_c = 1\text{ V}_{p-p}$ $f = 3.58\text{ MHz}$ S_4 off		5		V
Min. Chroma Out Level—Read P_8 $E_5 = 5\text{ V dc}$	$e_c = 1\text{ V}_{p-p}$ $f = 3.58\text{ MHz}$ S_4 on		10		V

Linear Integrated Circuits

CA3156E

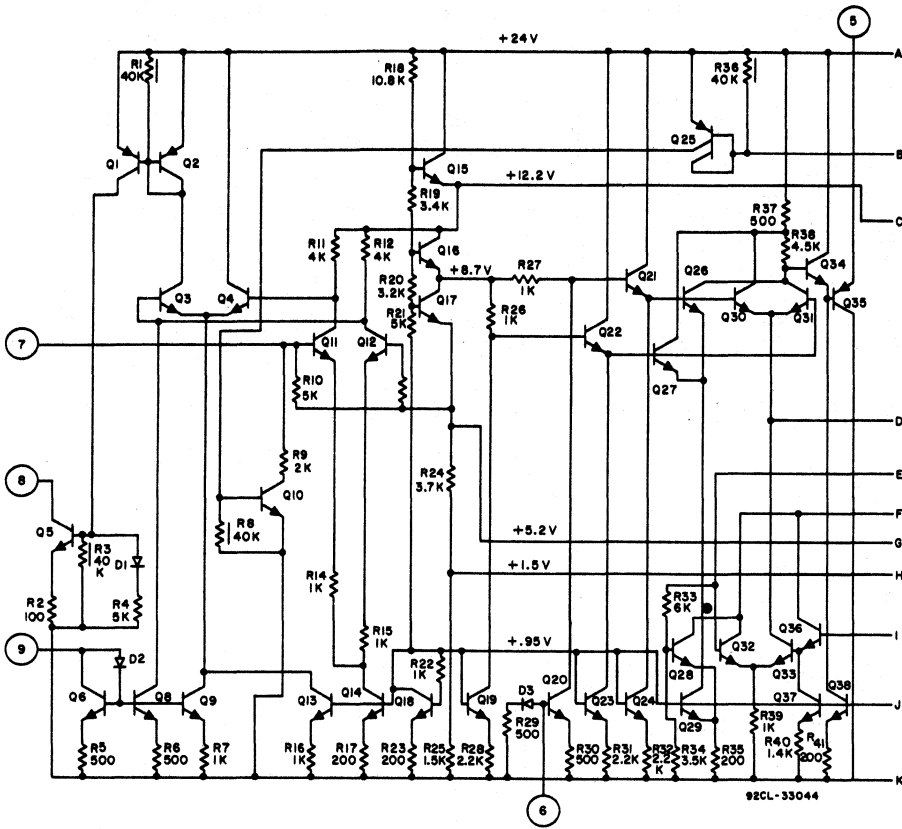


Fig. 2 - Schematic diagram of CA3156E.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE	30 V
DC SUPPLY CURRENT	21 mA
DEVICE DISSIPATION:	
Up to $T_A = 25^\circ\text{C}$750 mW
Above $T_A = 25^\circ\text{C}$	Derate linearly at 11.1 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:	
Operating	0 to 60 $^\circ\text{C}$
Storage	- 55 to 150 $^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 \pm 1/32 in. (1.59 \pm 0.79 mm) from case for 10 seconds max.	+ 265 $^\circ\text{C}$

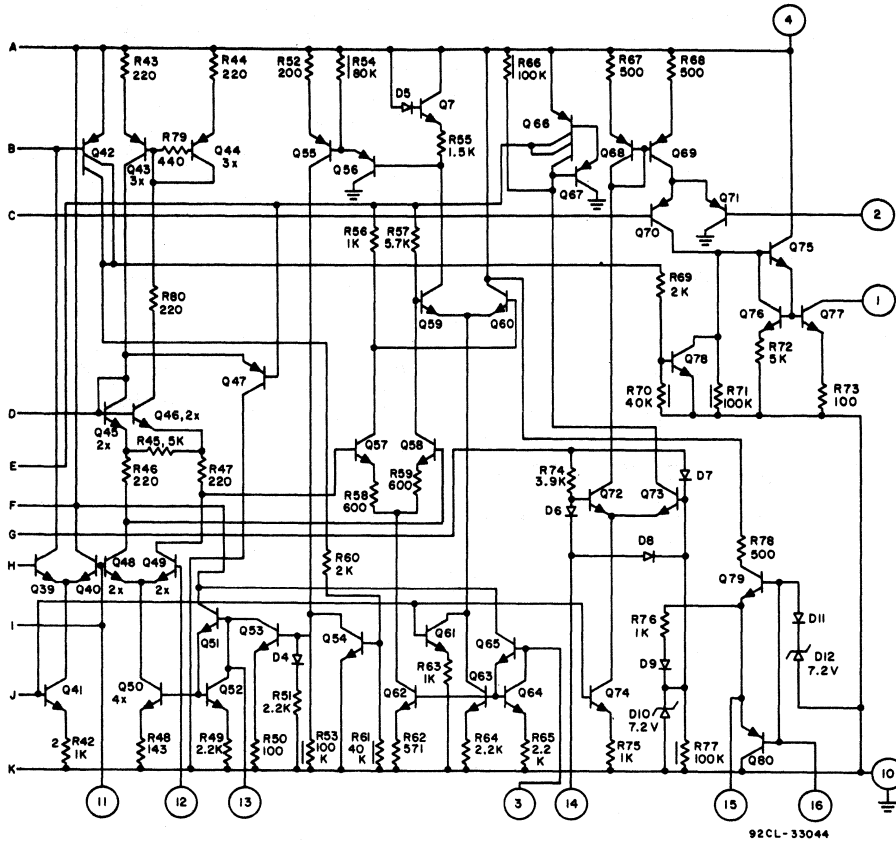
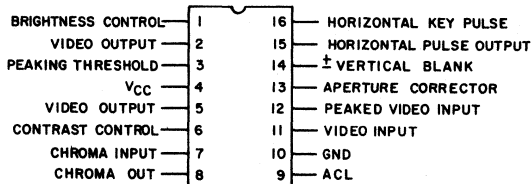


Fig. 2 - Schematic diagram (cont'd).

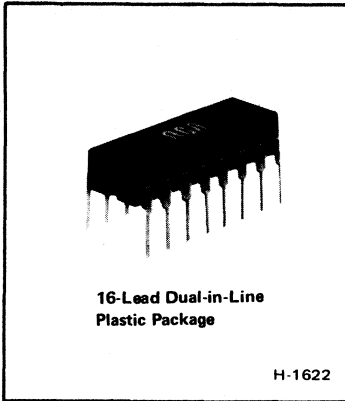


TOP VIEW

92CS-33042

Terminal Assignment

CA758



RC Phase-Lock-Loop Stereo Decoder

For FM Multiplex Systems

Features:

- Low distortion (THD): 0.4% (typ.)
- Excellent SCA rejection: 70 dB typ.
- RC oscillator
- High-audio-channel separation: 45 dB
- Power supply range: 10 to 16 V dc
- Requires only one adjustment for complete alignment
- Low-impedance outputs
- Stereo indicator lamp drive: 150 mA typ.

RCA-CA758E is a monolithic silicon integrated circuit RC phase-lock loop stereo decoder intended for FM solid-state stereo multiplex systems.

The CA758E is pin compatible and electrically equivalent to industry types μ A758, MC1311P, LM1800, and ULX2244.

The CA758E decodes the multiplexed stereo input signal into left and right channel audio output signals. The decoder also suppresses SCA (storecast) transmissions when present in the composite stereo signal.

The decoder uses a minimum of external components, and requires one adjustment (oscillator frequency) for complete alignment. In addition, the CA758E provides automatic mono-stereo mode switching and energizes a stereo indicator lamp.

The CA758E is supplied in a 16-lead dual-in-line plastic package and operates over an ambient temperature range of -40 to $+85^{\circ}\text{C}$.

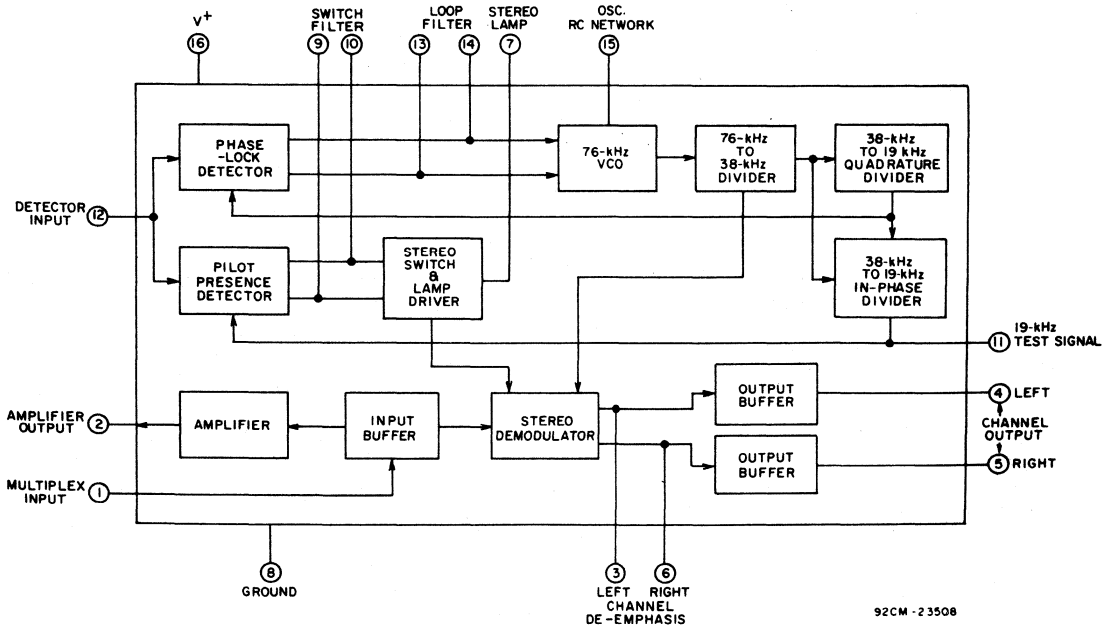


Fig. 1 - Functional block diagram of the CA758E.

MAXIMUM RATINGS, *Absolute-Maximum Values at $T_A = 25^\circ\text{C}$*

DC Supply Voltage	+18 V
DC Supply Voltage (for \leq a 15-second period)	+22 V
DC Voltage at Term. 7 (Lamp Driver Circuit with Lamp "OFF")	+22 V
Device Dissipation:	
Up to $T_A = 70^\circ\text{C}$	730 mW
Above $T_A = 70^\circ\text{C}$ derate linearly	9.1 mW/ $^\circ\text{C}$
Ambient Temperature Range:	
Operating	-40 to +85 $^\circ\text{C}$
Storage	-65 to +150 $^\circ\text{C}$
Lead Temperature (During soldering):	
At a distance not less than 1/32" (0.79 mm)	
from case for 10 s max.	+265 $^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	TEST CONDITIONS (Referenced to Fig. 3 unless otherwise specified) $V^+ = 12\text{ V}, T_A = 25^\circ\text{C}$ Multiplex Input Signal (L=R, pilot "OFF") = 300 mV RMS 19-kHz Pilot Level = 30 mV RMS f (modulation) = 400 Hz or 1 kHz	LIMITS			UNITS
		Min.	Typ.	Max.	
Static Characteristics					
Total Current	Lamp "OFF"	—	26	35	mA
Maximum Available Lamp Current		75	150	—	mA
DC Voltage at Term. 7 (Lamp Driver)	I (Lamp) = 50 mA	—	1.3	1.8	V
DC Voltage Shift at either Term. 4 or 5 (Output)	Stereo-to-Mono Operation	—	30	150	mV
Dynamic Characteristics					
Power Supply Ripple Rejection	For a 200-Hz, 200-mV RMS Signal	35	45	—	dB
Input Resistance		20	35	—	k Ω
Output Resistance		0.9	1.3	2.0	k Ω
Channel Separation (Stereo)	At f = 100 Hz	—	40	—	dB
	f = 400 Hz	30	45	—	dB
	f = 10 kHz	—	45	—	dB
Channel Balance (Monaural)		—	0.3	1.5	dB
Voltage Gain	At f = 1 kHz	0.5	0.9	1.4	V/V
Pilot Input Level:					
19-kHz Input	Lamp "ON"	—	15	20	mV RMS
19-kHz Input	Lamp "OFF"	2.0	7.0	—	mV RMS
Hysteresis	Lamp "OFF"	3.0	7.0	—	dB
Capture Range (Deviation from 76-kHz Center Frequency)		± 2.0	± 4.0	± 6.0	%
Total Harmonic Distortion	Multiplex Input Signal = 600 mV RMS (Pilot "OFF")	—	0.4	1.0	%
19-kHz Rejection		25	35	—	dB
38-kHz Rejection		25	45	—	dB
SCA (Storecast) Rejection	Measured Composite Signal: 80% Stereo, 10% Pilot, 10% SCA	—	70	—	dB
Voltage-Controlled Oscillator (VCO) Tuning Resistance	Total Resistance (Term. 15 to 8) required to set $f_{\text{REF}} = 19\text{ kHz} \pm 10\text{ Hz}$ (Term. 11)	21.0	23.3	25.5	k Ω
Voltage-Controlled Oscillator Frequency Drift	$0^\circ \leq T_A \leq 25^\circ\text{C}$	—	+0.1	± 2	%
	$25^\circ \leq T_A \leq 70^\circ\text{C}$	—	-0.4	± 2	%

CA758

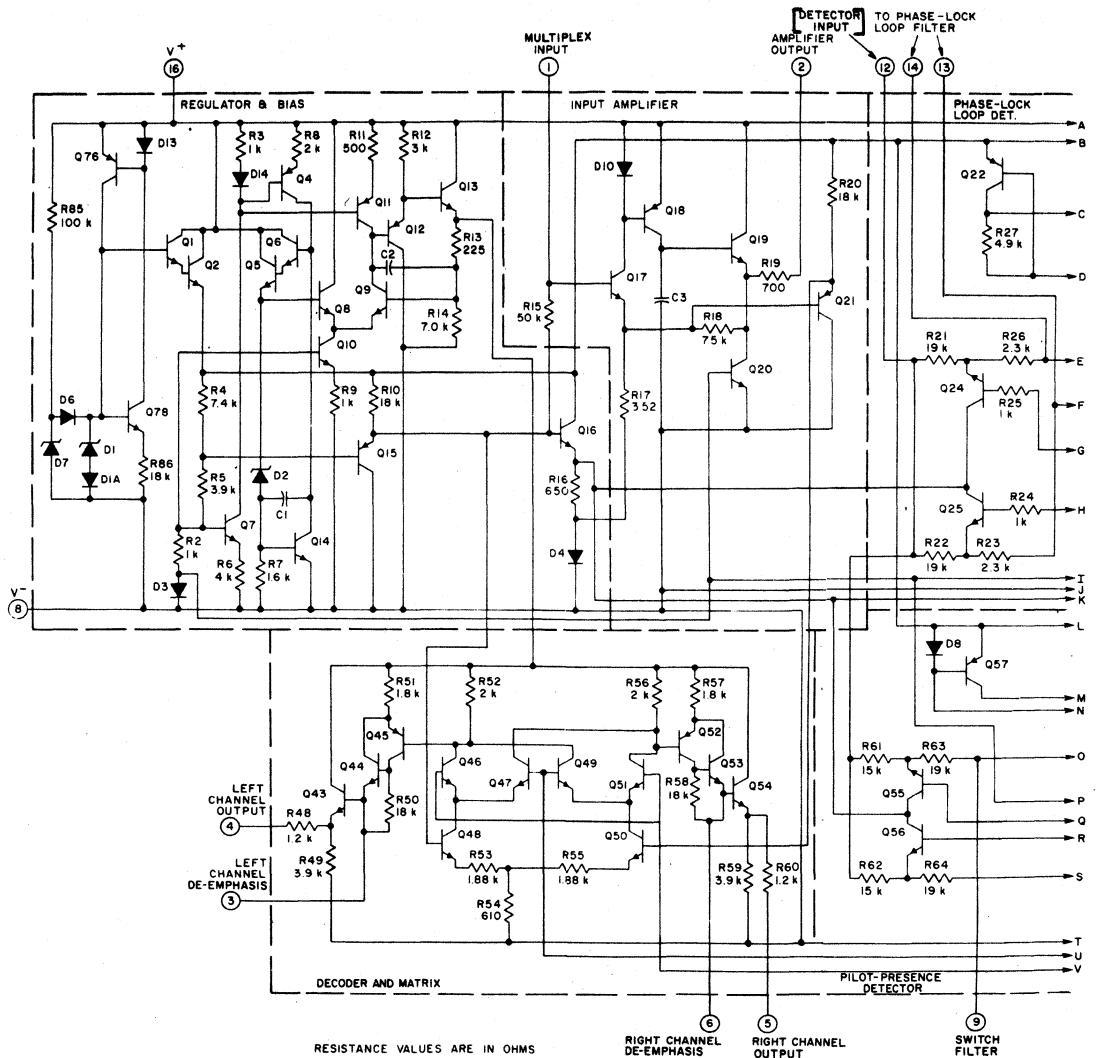


Fig. 2 - Schematic diagram of the CA758E.

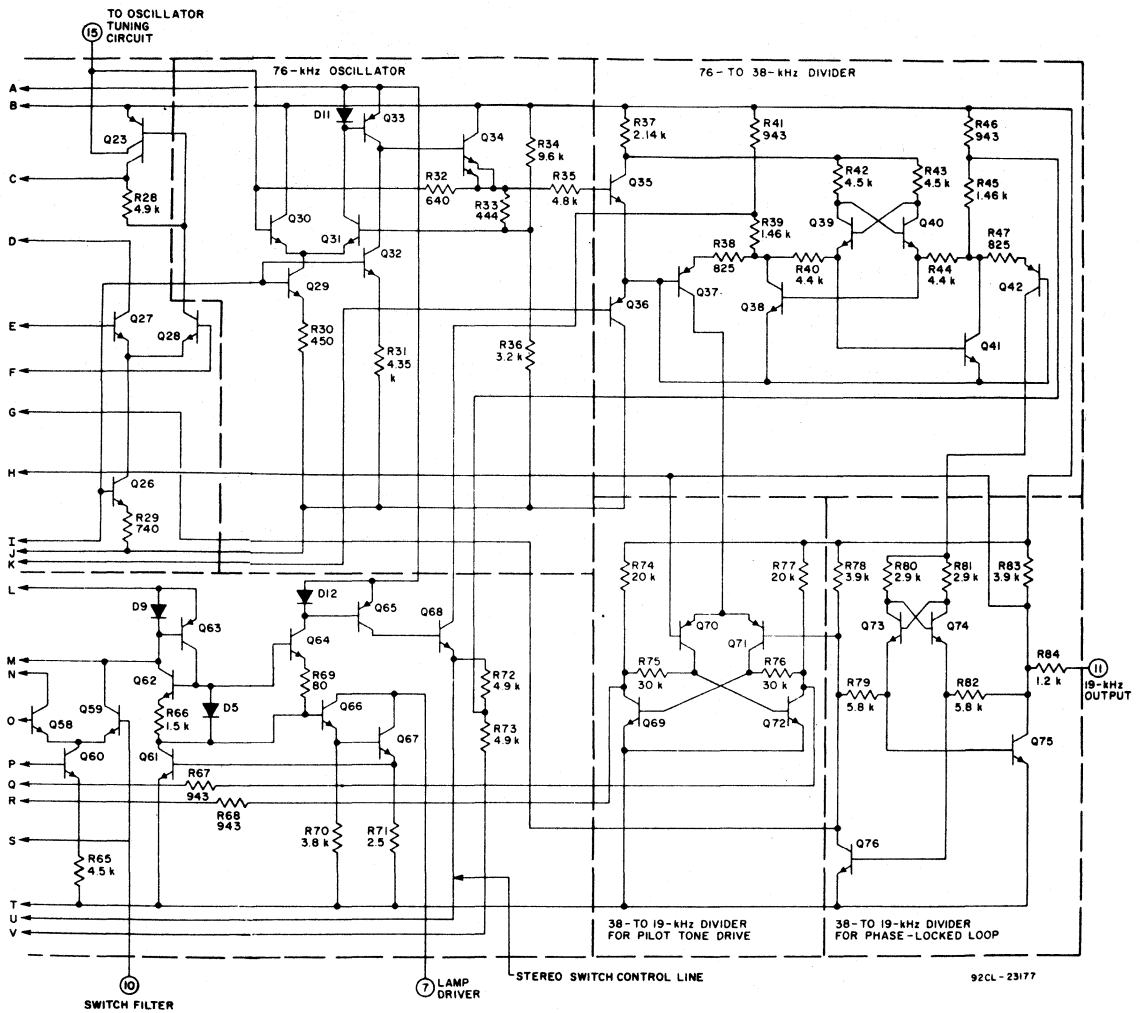


Fig. 2 - Schematic diagram of the CA758E (Cont'd).

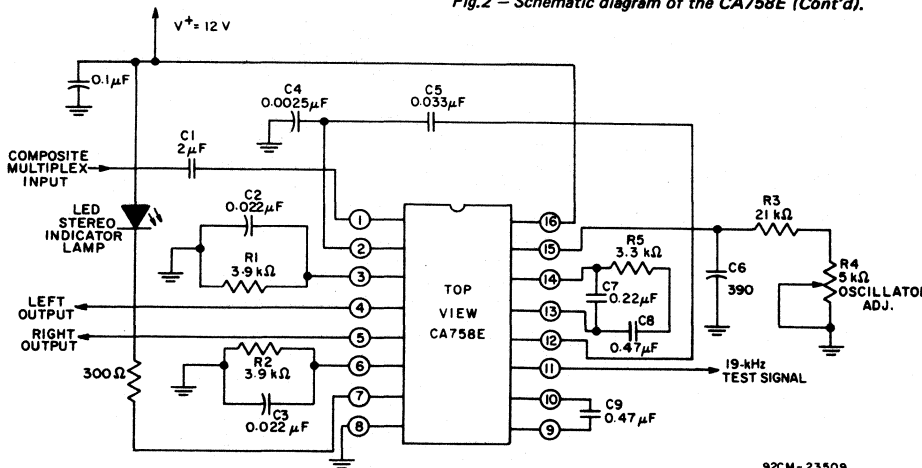


Fig. 3 - Test circuit for measurement of dynamic characteristics.

NOTES:

- Tolerance on resistors is $\pm 5\%$ and tolerance on capacitors is $\pm 20\%$ unless otherwise specified.
- $C_1 = +100\%, -20\%$
- $C_6 = \pm 1\%$ in test circuit and $\pm 5\%$ in typical application.
- $R_3 = \pm 1\%$
- $R_4 = \pm 10\%$
- R_1 and $R_2 = \pm 1\%$ in test circuit and $\pm 5\%$ in typical application.

92CM-23509

CA758

TYPICAL PERFORMANCE CHARACTERISTICS (Referenced to Fig. 3)

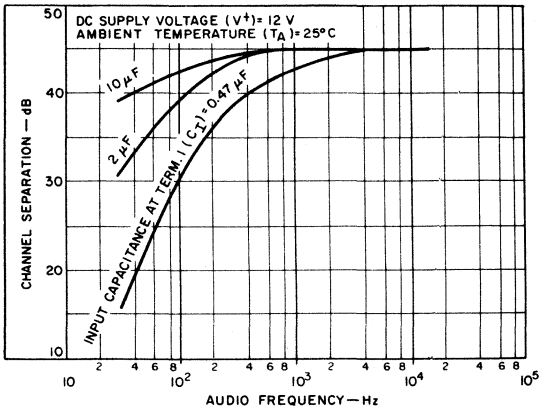


Fig. 4 - Channel separation vs. audio frequency.

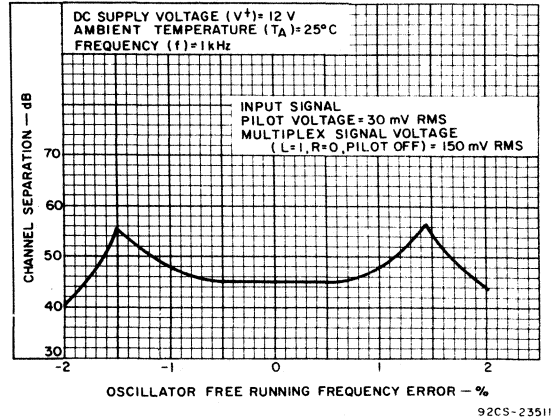


Fig. 5 - Channel separation vs. oscillator free running frequency error.

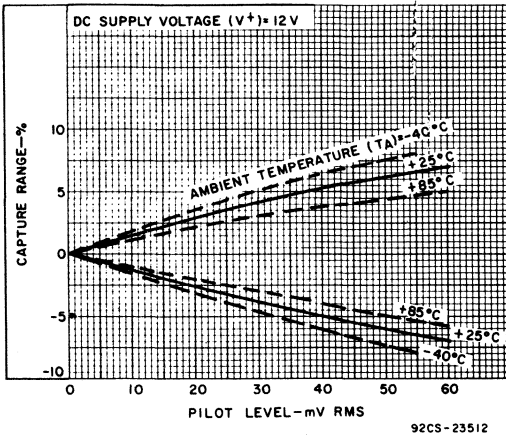


Fig. 6 - Capture range vs. pilot level.

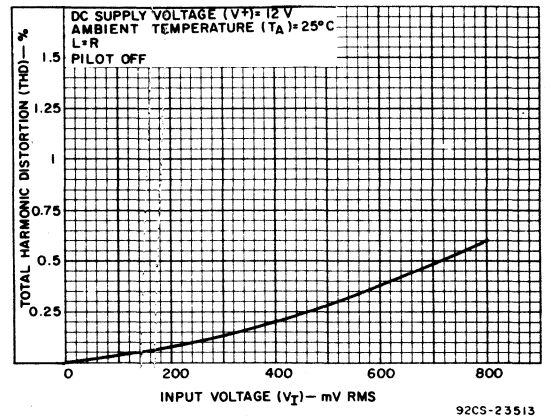


Fig. 7 - Total harmonic distortion vs. input level.

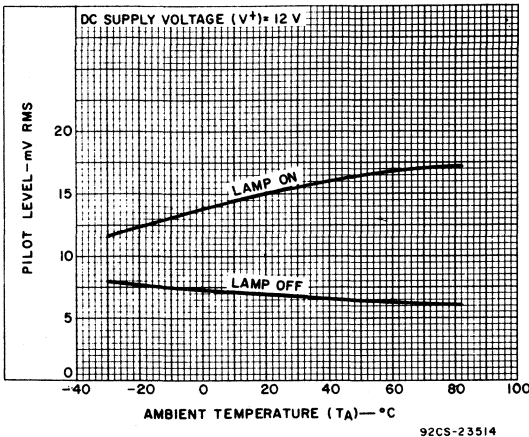


Fig. 8 - Lamp turn-on and turn-off sensitivity vs. ambient temperature.

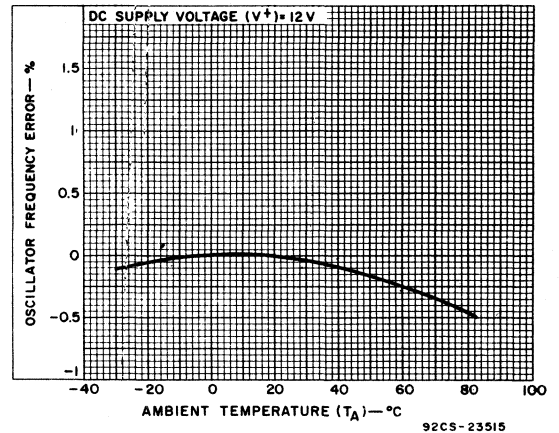
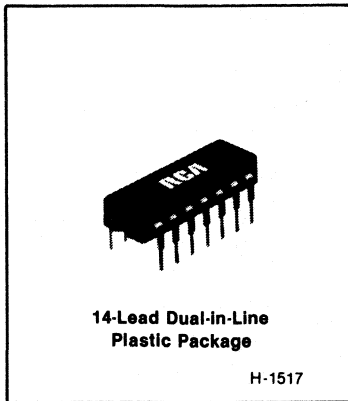


Fig. 9 - Oscillator free running frequency error vs. ambient temperature.



RC Phase-Lock-Loop Stereo Decoder

For FM Multiplex Systems

Features:

- Low distortion [THD]: 0.3% typ.
- Excellent SCA [storecast] rejection: 75 dB typ.
- RC oscillator
- High audio channel separation: 40 dB
- Operates from a wide range of power supplies: 8 to 16 V dc
- Requires only one adjustment for complete alignment
- Drives a stereo indicator lamp up to 75 mA - surge current limiting
- Stereo separation maintained with 8-volt supply voltages

RCA-CA1310A is a monolithic silicon integrated circuit RC phase-lock-loop stereo decoder intended for FM solid-state stereo multiplex systems. It is a direct replacement for industry types MC1310P, LM1310, and SN76115N.

This decoder uses a minimum of external components. In addition the stereo decoder requires only one adjustment (oscillator frequency) for complete alignment.

The CA1310A is unilaterally interchangeable with the CA1310 and offers improved and controlled distortion char-

acteristics. A maximum limit of 1% is guaranteed over the V_{CC} range of 8 to 16 volts under any conditions of modulation ($L = R$, $L = -R$, $L = 1$, $R = 0$, or $L = 0$, $R = 1$). The local oscillator stability has also been improved so that stereo separation is maintained with supply voltages as low as 8 volts.

The CA1310A is supplied in a 14-lead dual-in-line plastic package and operates over an ambient temperature range of -40 to $+85^{\circ}\text{C}$.

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^{\circ}\text{C}$:

DC SUPPLY VOLTAGE	16 V
CURRENT (LAMP) AT TERM. 6	75 mA
DEVICE DISSIPATION:	
Up to $T_A = 25^{\circ}\text{C}$	625 mW
Above $T_A - 25^{\circ}\text{C}$ derate linearly	5 mW/ $^{\circ}\text{C}$
AMBIENT TEMPERATURE RANGE:	
Operating	-40 to $+85^{\circ}\text{C}$
Storage	-65 to $+150^{\circ}\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance not less than 1/32" (0.79 mm) from case for 10 s max	$+265^{\circ}\text{C}$

Linear Integrated Circuits

CA1310E

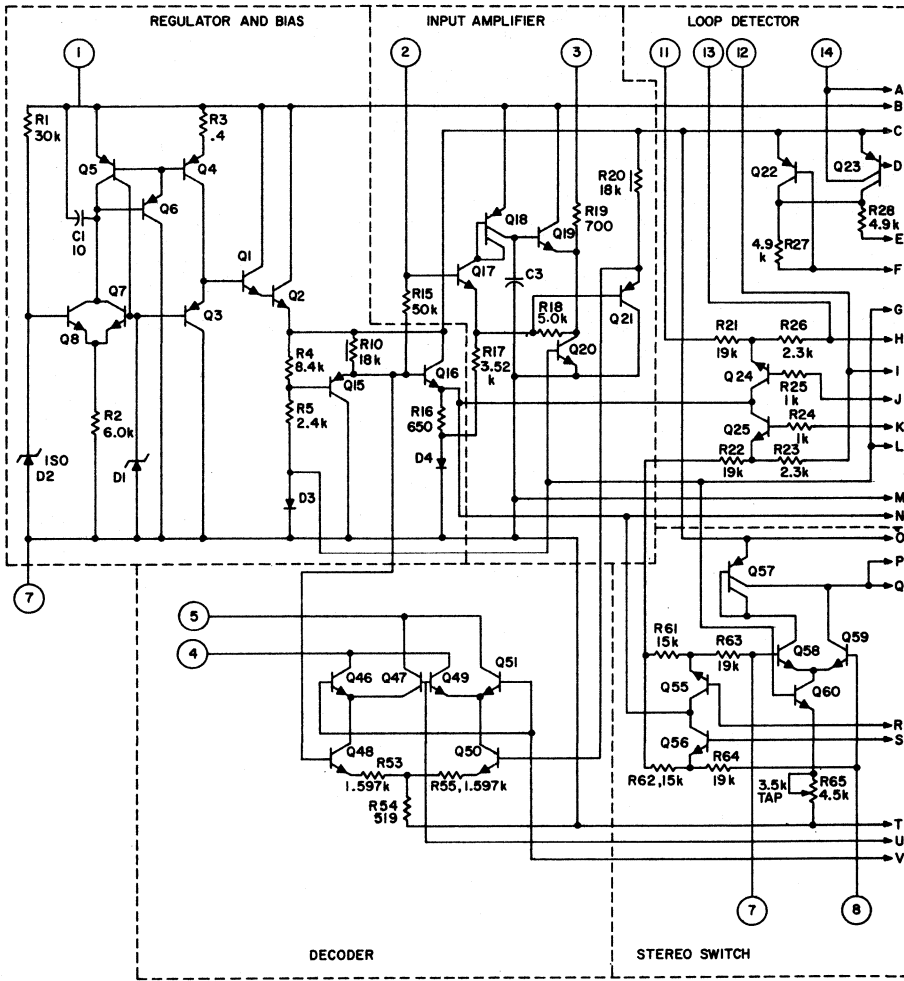
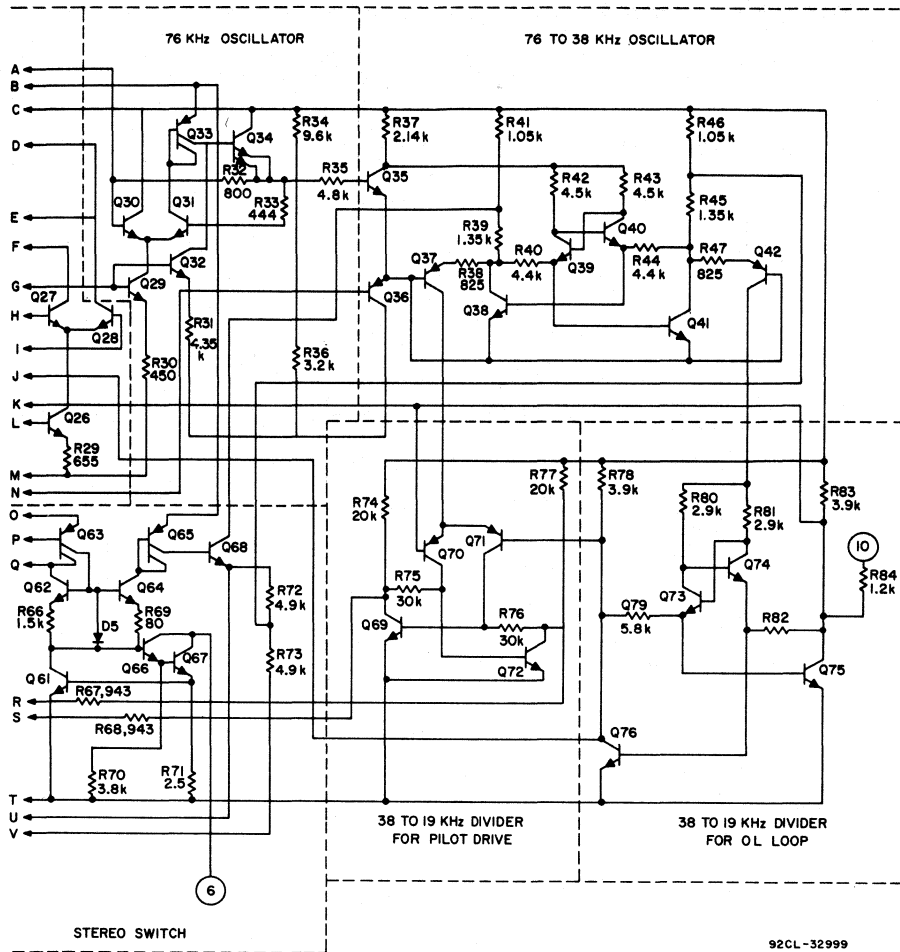


Fig. 1 — Schematic diagram of the CA1310A.



92CL-32999

Fig. 2—Schematic diagram of the CA1310A (cont'd).

Linear Integrated Circuits

CA1310E

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	TEST CONDITIONS (Referenced to Fig. 3) $V^+ = 12\text{ V}$ $T_A = 25^\circ\text{C}$ Composite Multiplex Input Signal 2.8 V p-p.	LIMITS			UNITS
		Min.	Typ.	Max.	
		Static Characteristics			
DC Supply Voltage	For 8-V operation, reduce load to 2.7 k Ω	8	—	16	V
Total Current	Lamp "OFF"	—	13	—	mA
Dynamic Characteristics					
Input Impedance		20	50	—	k Ω
Channel Separation (Stereo)	50 Hz — 15 kHz	30	40	—	dB
Audio Output Voltage (For any one channel)		—	485	—	mV RMS
Channel Balance (Monaural)	Pilot Tone "OFF"	—	—	1.5	dB
Capture Range (Permissible tuning error of internal oscillator)		—	± 3.5	—	%
Total Harmonic Distortion		—	0.3	1.0	%
Ultrasonic Frequency Rejection:					
19 kHz		—	34.4	—	dB
38 kHz		—	45	—	dB
SCA (Storecast) Rejection	$f = 67\text{ kHz}$, 9-kHz beat note measured with 1-kHz modulation "OFF"	—	75	—	dB
Stereo Switch Level:					
19-kHz Input Level (For lamp on)		—	—	20	mV RMS
19-kHz Input Level (For lamp off)		5	—	—	mV RMS

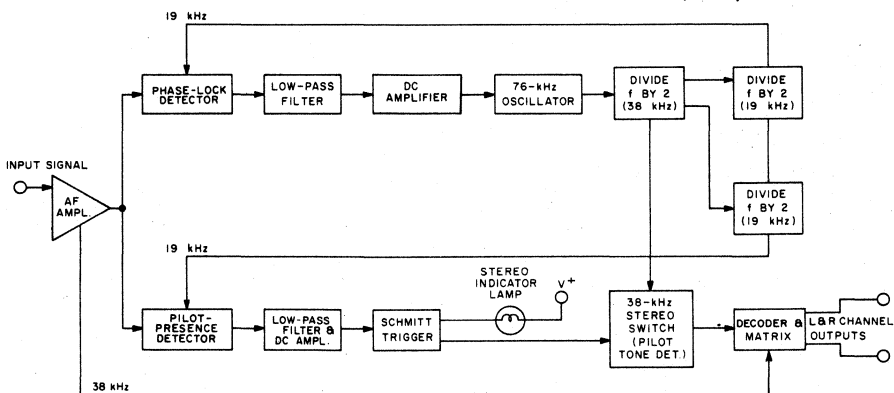
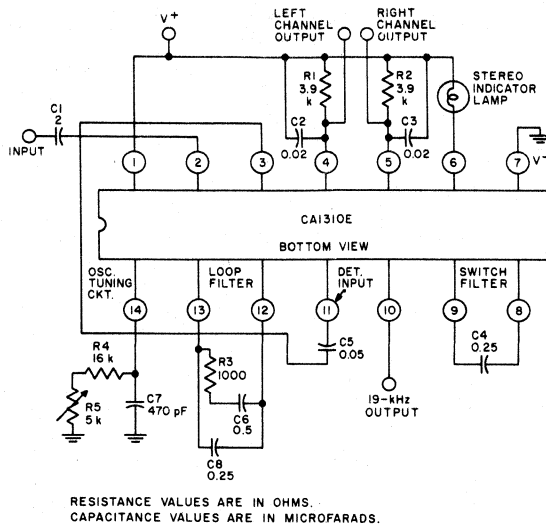


Fig. 2— Functional block diagram of the CA1310A system.

92CS-23500



92CS-2350I

Fig. 3—Test circuit for measurement of dynamic characteristics.

NOTES for test circuit of Fig. 3.

A buffered 3-volt positive-going square wave is available at Term. 10. The alignment of the free-running oscillator frequency may be checked at this point with a frequency counter.

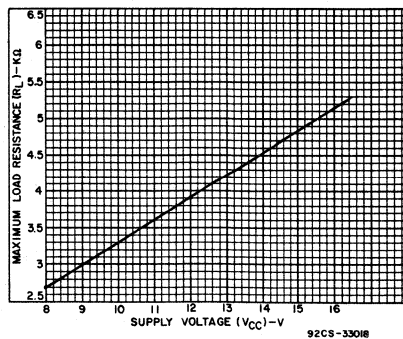
C1: A lower-value input coupling capacitor may be used in place of the 2- μ F value if reduced separation at low frequencies is acceptable.

C4: The time constant for the stereo-switch level-detector circuit is calculated by $C4 \times 53,000$ ohms $\pm 30\%$ with a maximum dc voltage drop across C4 of 0.25 volt (Term. 8 positive) and a pilot-level voltage of 100 mV RMS. Signal voltage across C4 is negligible.

C5: The recommended 0.05- μ F capacitor provides a 1.75° phase lead at 19 kHz.

R3, C6, C8: C8 may be omitted, R3 = 100 ohms and C6 = 0.25 μ F, if relaxed circuit performance is acceptable.

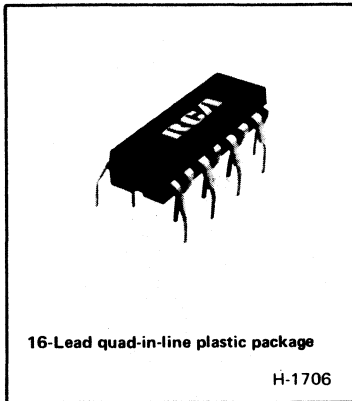
R4, R5, C7: If a capture range greater than $\pm 3\%$ typ. is required, reduce value of C7 and increase values of R4 and R5 proportionally. However, beat-note distortion is increased at high signal levels because of oscillator-phase jitter. The tolerances of R4 and C7 are $\pm 1\%$ in the test circuit and $\pm 5\%$ in typical application circuits.



92CS-3301E

Fig. 4—Maximum load resistance vs. supply voltage.

CA3090AQ



Stereo Multiplex Decoder

For FM Stereo Multiplex Systems

FEATURES:

- Requires the use of only one low-inductance tuning coil
- Automatic stereo switching
- Directly drives a stereo indicator lamp up to 100 mA
- Includes driver for stereo-lamp indicator
- Operates from a wide range of power supplies: 10 to 16 volts
- Requires only one adjustment for alignment
- Switching from monaural to stereo and stereo to monaural produces no audible thumps

RCA-CA3090AQ*, a monolithic silicon integrated circuit, is a stereo multiplex decoder intended for FM multiplex systems.

The CA3090AQ is the successor to the CA3090Q; it offers three major advantages over the CA3090Q as follows:

1. Can directly drive a stereo indicator lamp with a current drain of up to 100 mA.
2. Stereo Defeat/Enable control-voltage specifications.
3. Capable of operation with lower distortion.

This stereo multiplex decoder requires only one low-inductance tuning coil (requires only one adjustment for complete alignment), provides automatic stereo switching, energizes a stereo indicator lamp, and operates from a wide range of voltage supplies.

Figure 1 shows the block diagram for the CA3090AQ. The input signal from the detector is amplified by a low-distortion preamplifier and simultaneously applied to both the 19-kHz and 38-kHz synchronous detectors. A 76-kHz signal, generated by a local voltage-controlled oscillator (VCO), is counted down by two frequency dividers to a 38-kHz signal and to two 19-kHz signals in phase quadrature. The 19-kHz pilot-tone supplied by the FM detector is compared to the locally generated 19-kHz signal in a synchronous detector. The resultant signal controls the voltage controlled oscillator (VCO) so that it produces an output signal to phase-lock the stereo decoder with the pilot tone. A second synchronous detector compares the locally generated 19-kHz signal with the 19-kHz pilot tone. If the pilot tone exceeds an externally adjustable threshold voltage, a Schmitt trigger circuit is energized. The signal from the Schmitt trigger lights the stereo indicator, enables the 38-kHz synchronous detector, and automatically switches the CA3090AQ from monaural to stereo operation. The output signal from the 38-kHz detector and the composite signal from the preamplifier are applied to a

- Low distortion: under 0.5%
- Separate dc input permits stereo defeat or enable
- High signal output: directly drives audio amplifiers
- Excellent SCA (storecast) rejection: 55 dB typ.
- High audio channel separation: 40 dB typ.

matrixing circuit from which emerge the resultant left and right channel audio signals. These signals are applied to their respective left and right post amplifiers for amplification to a level sufficient to drive most audio amplifiers.

The CA3090AQ may be used without the stereo defeat/enable function (see Fig. 6) if a control voltage for this function is not readily available. In this case, Terminal 4 should be grounded.

The CA3090AQ utilizes the 16-lead quad-in-line plastic package and operates over the ambient temperature range of -40°C to $+85^{\circ}\text{C}$.

*Formerly Developmental Type No. TA6262G.

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^{\circ}\text{C}$:

DC Supply Voltage	16 V
Current at Term. 12	100 mA
Input Signal Voltage (Composite)■	400 mV
Ambient Temperature Range:	
Operating	-40 to $+85^{\circ}\text{C}$
Storage	-65 to $+150^{\circ}\text{C}$
Lead Temperature (during soldering):	
At distance not less than 1/32" (0.79 mm)	
from case for 10 s max.	$+265^{\circ}\text{C}$

■ For stereo operation, a minimum input signal voltage (composite) of 40 mV is required.

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	TERMINAL MEASURED AND SYMBOL	TEST CONDITIONS			LIMITS			UNITS
		Typ. Char. Curve Fig. No.	T _A = 25°C V ⁺ = 12 V (unless specified otherwise)	Circuit Fig. No.	Min.	Typ.	Max.	
Static Characteristics								
Total Current (Terms. 9, 10, 11)	I _{total}		Lamp OFF	3	—	22	27	mA
DC Voltage:								
Term. 1	V ₁			3	1.6	2.3	3.1	V
Term. 6 (Indicator Lamp OFF)	V ₆			3	—	2.1	3.6	V
Terms. 9 and 10	V _{9 & 10}			3	3.7	5.4	7.4	V
Term. 12 (Indicator Lamp OFF)	V ₁₂		V ⁺ = 16 V		12.7	—	—	V
Voltage Differential (Term. 2—Term. 1)	V ₂ - V ₁			3	—	0	0.1	V
Current at Term. 12 (In actual use external circuit resistance (e.g. lamp should limit Term. 12 to the maximum rated value of 100 mA.)		4	V _{IN} (at f = 19 kHz) = 18 mV	1	75	100	—	mA
Dynamic Characteristics								
Input Impedance	Z _{IN}			7	—	50k	—	Ω
Channel Separation (L + R Reference)*				7	25	40	—	dB
Channel Balance (Monaural)				7	—	0.3	3	dB
Monaural Gain			V _{IN} = 180 mV		3	6	9	dB
Stereo/Monaural Gain Ratio*				7	—	±0.3	±3	dB
Indicator Lamp - Turn-ON Voltage		5	19-kHz pilot-tone @ Term. 1	7	—	4	—	mV
Capture Range (Deviation from 76-kHz center frequency)		7, 8	19-kHz pilot-tone voltage = 18 mV	7	±6.6	±10	—	%
Distortion (75-μs de-emphasis):								
2nd Harmonic			V _{IN} = 240 mV	7	—	0.2	—	%
3rd, 4th, and 5th Harmonic				7	—	<0.1	—	%
19-kHz Rejection				7	—	35	—	dB
38-kHz Rejection				7	—	25	—	dB
SCA (storecast) Rejection				7	—	55	—	dB
Stereo Defeat Voltage (V ₄)					—	—	<0.9	V
Stereo Enable Voltage (V ₄)					>1.6	—	—	V

NOTE: For improved pilot sensitivity and overload characteristics, replace the .039 μF capacitor between Terminals 7 and 8 with a Series L-C Network (L = 4.7 mH, C = 0.015 μF). Under these conditions, Indicator Lamp Sensitivity: 'ON' = 3.3 mV, 'OFF' = 2.0 mV

* For stereo operation, test conditions require a composite stereo input signal (modulated at 1 kHz) including a 19-kHz (18 mV) pilot-tone signal.

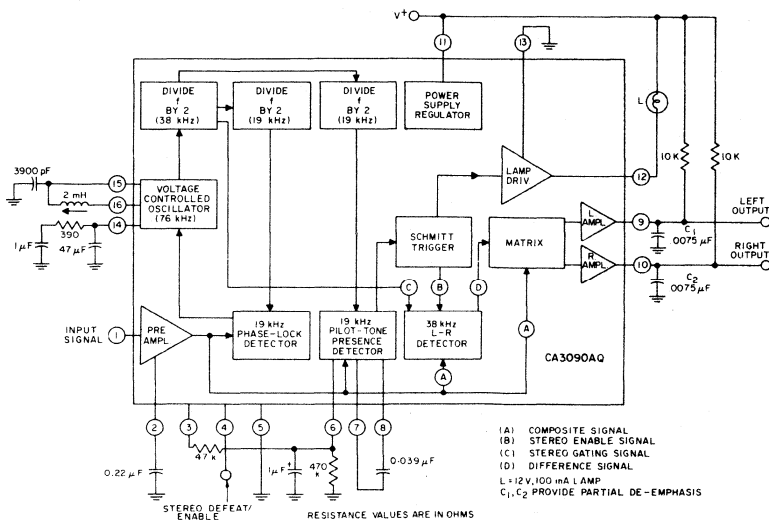


Fig. 1 - Functional block diagram of the CA3090AQ.

Linear Integrated Circuits

CA3090AQ

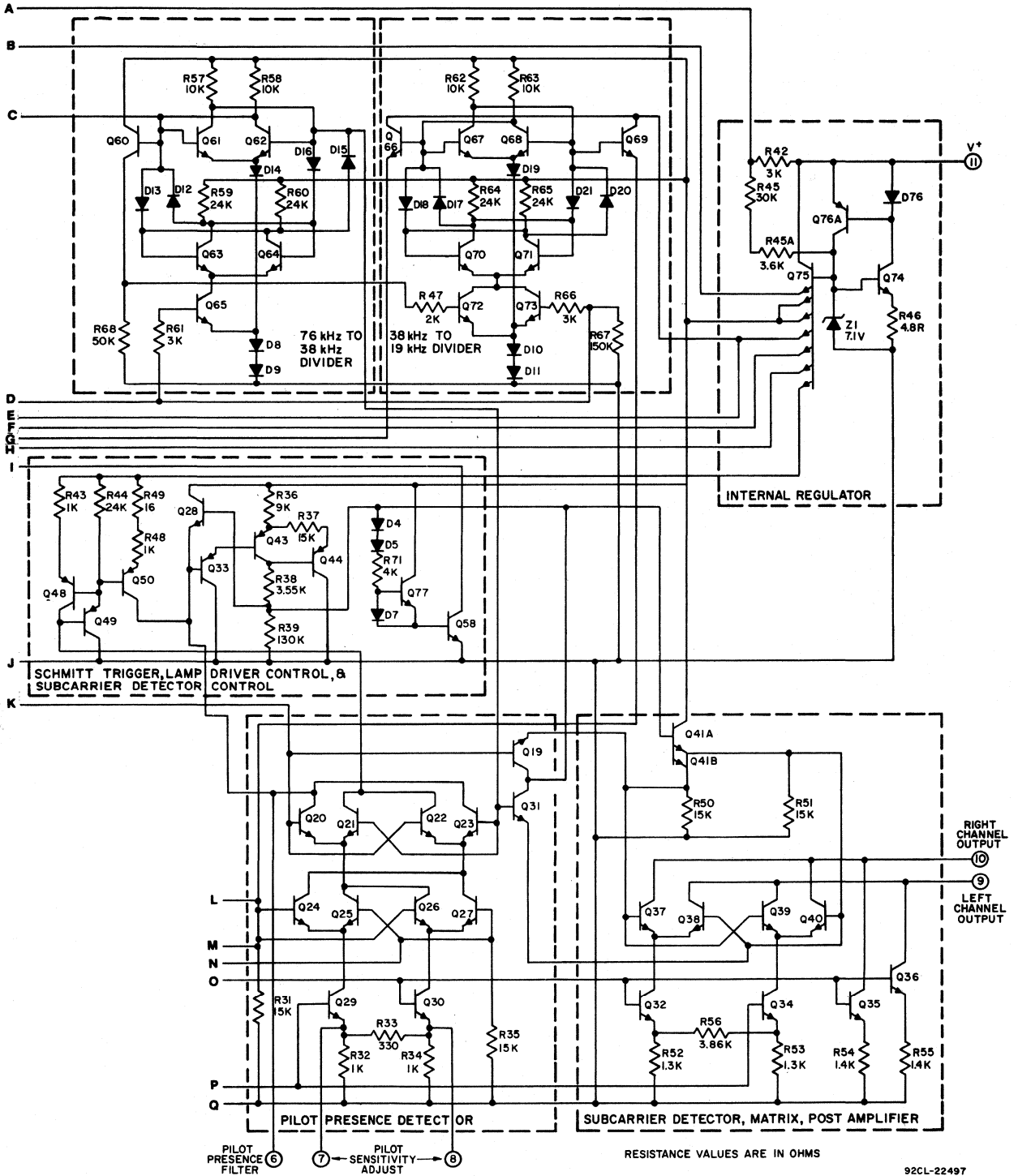
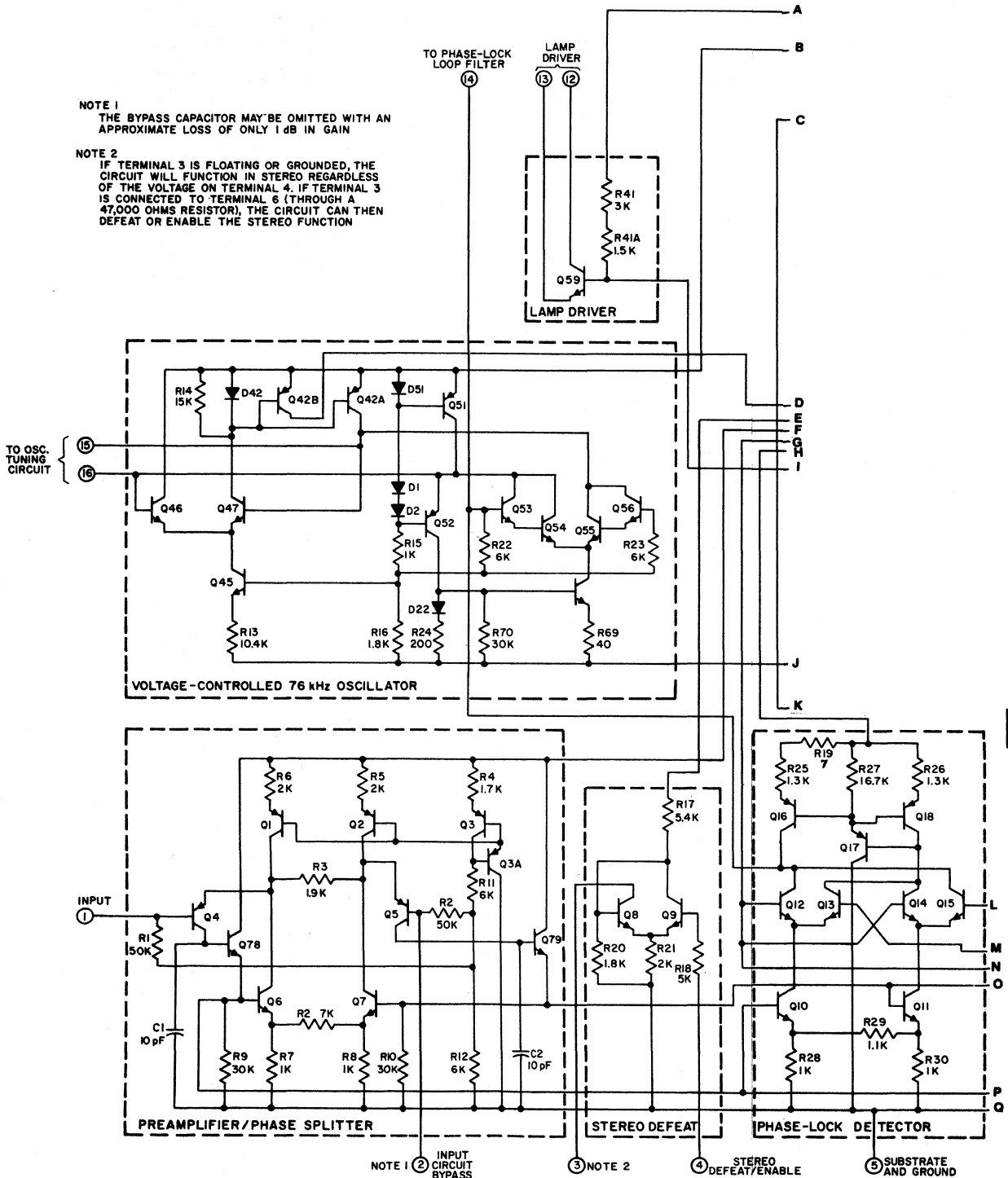


Fig. 2 - Schematic diagram of the CA3090AQ (cont'd from previous page).

92CL-22497



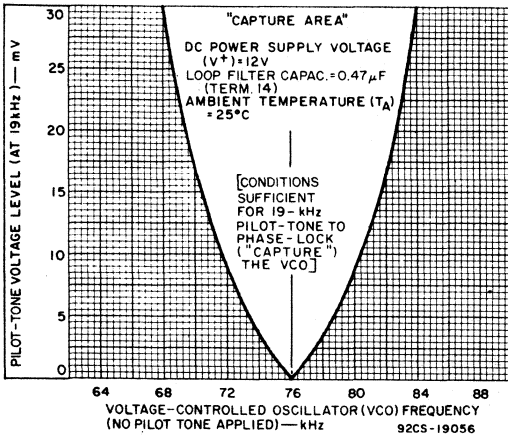


Fig. 8 - Pilot-tone voltage level vs. VCO frequency with no pilot-tone applied.

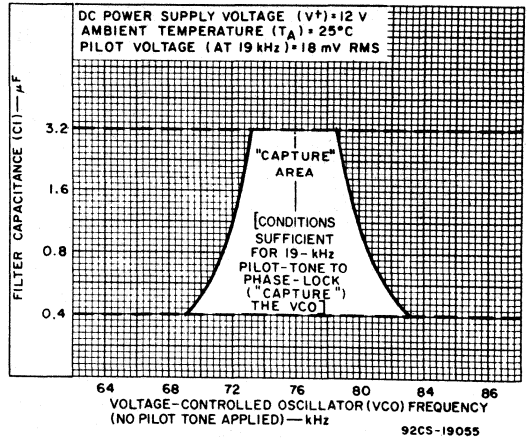
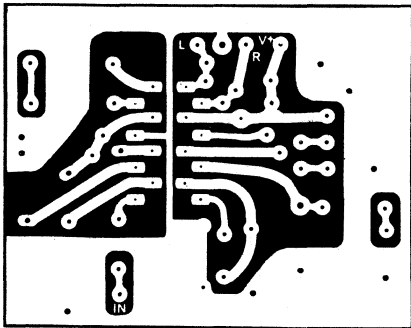
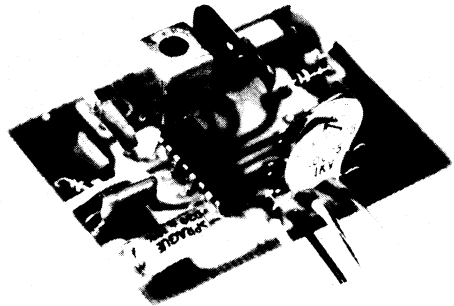


Fig. 9 - Filter capacitance vs. VCO frequency with no pilot-tone applied.



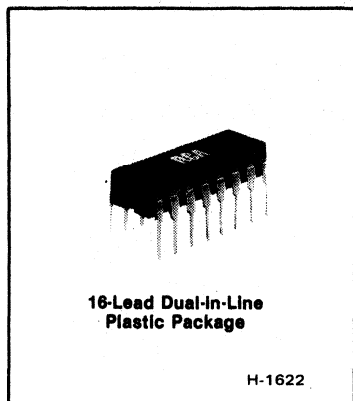
A - Foil side.



B - Component side.

Fig. 10 - Photographs of the CA3090AQ and outboard components mounted on a 2 X 2½-inch printed-circuit board to constitute a complete stereo multiplex decoder.

CA3195



RC Phase-Lock-Loop Stereo Decoder

For FM Multiplex Systems

Features:

- Low distortion (THD): 0.4% (typ.)
- Excellent SCA rejection: 70 dB typ.
- RC oscillator
- High-audio-channel separation: 45 dB
- Power supply range: 10 to 16 V dc
- Requires only one adjustment for complete alignment
- Low-impedance output: 40 Ω (typ.) resistance
- Stereo indicator lamp drive: 150 mA typ.

RCA-CA3195 is a monolithic silicon integrated circuit RC phase-lock loop stereo decoder intended for FM solid-state stereo multiplex systems.

The CA3195 is similar to the CA758. The CA3195 output resistance is much lower, making it capable of driving low impedance loads without buffering.

The CA3195 decodes the multiplexed stereo input signal into left and right channel audio output signals. The decoder also suppresses SCA (storecast) transmissions when present in the composite stereo signal.

The decoder uses a minimum of external components, and requires one adjustment (oscillator frequency) for complete alignment. In addition, the CA3195 provides automatic mono-stereo mode switching and energizes a stereo indicator lamp.

The CA3195 is supplied in a 16-lead dual-in-line plastic package and operates over an ambient temperature range of -40 to +85°C.

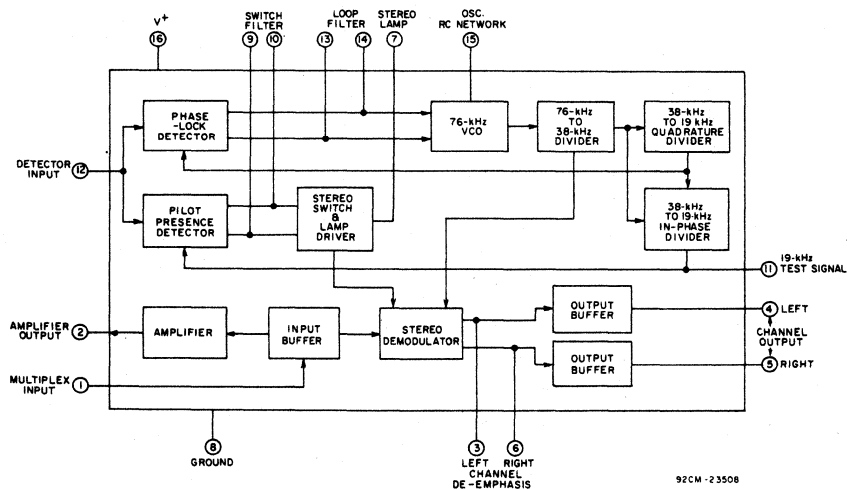


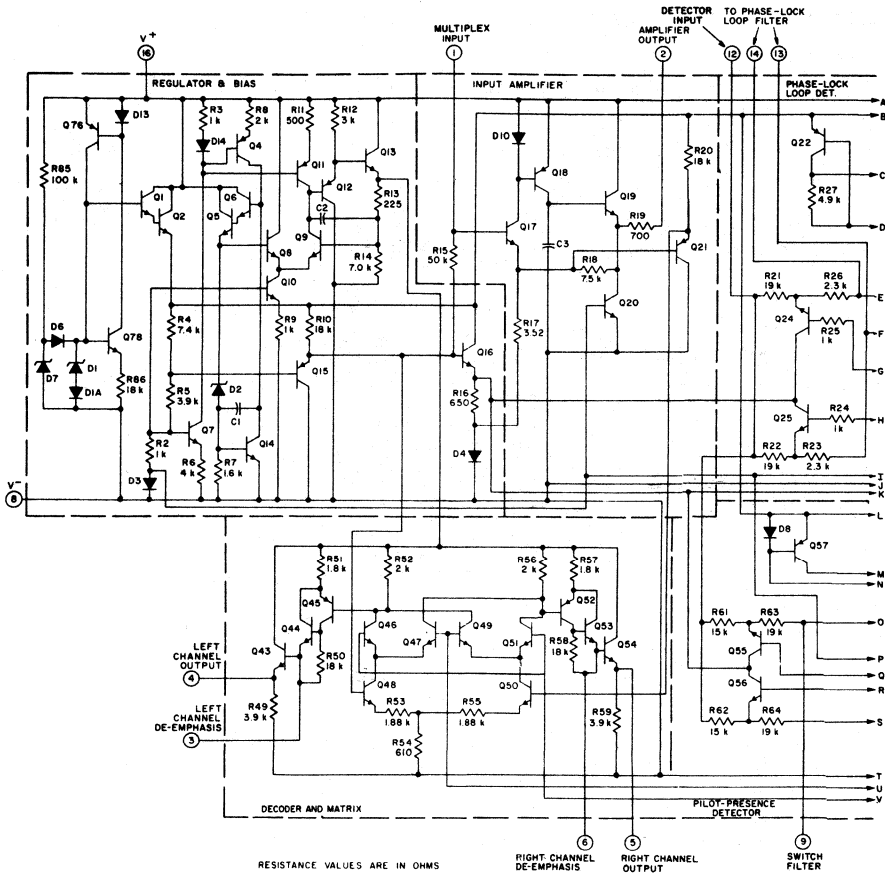
Fig. 1 — Functional block diagram of the CA3195.

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

DC Supply Voltage	+18 V
DC Supply Voltage (for \leq a 15-second period)	+22 V
DC Voltage at Term. 7 (Lamp Driver Circuit with Lamp "OFF")	+22 V
Device Dissipation:	
Up to $T_A = 70^\circ\text{C}$	730 mW
Above $T_A = 70^\circ\text{C}$ derate linearly	9.1 mW/ $^\circ\text{C}$
Ambient Temperature Range:	
Operating	-40 to +85 $^\circ\text{C}$
Storage	-65 to +150 $^\circ\text{C}$
Lead Temperature (During soldering):	
At a distance not less than 1/32" (0.79 mm) from case for 10 s max.	+265 $^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

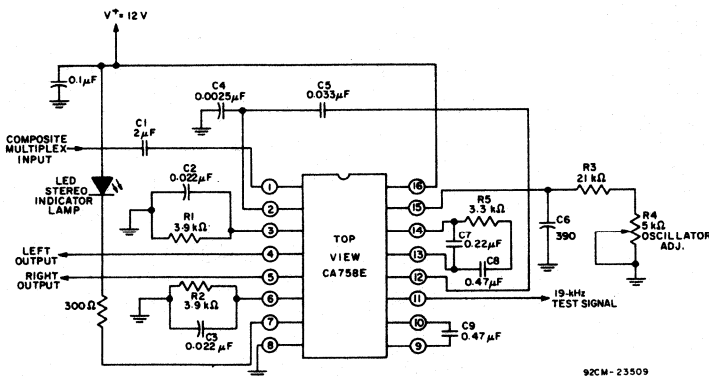
CHARACTERISTIC	TEST CONDITIONS (Referenced to Fig.3 unless otherwise specified) $V^+ = 12\text{ V}, T_A = 25^\circ\text{C}$ Multiplex Input Signal (L = R, pilot "OFF") = 300 mV RMS 19-kHz Pilot Level = 30 mV RMS f (modulation) = 400 Hz or 1kHz	LIMITS			UNITS
		Min.	Typ.	Max.	
Static Characteristics					
Total Current	Lamp "OFF"	—	26	35	mA
Maximum Available Lamp Current		75	150	—	mA
DC Voltage at Term. 7 (Lamp Driver)	1 (Lamp) = 50 mA	—	1.3	1.8	V
DC Voltage Shift at either Term.4 or 5 (Output)	Stereo-to-Mono Operation	—	30	150	mV
Dynamic Characteristics					
Power Supply Ripple Rejection	For a 200-Hz, 200-mV RMS Signal	35	45	—	dB
Input Resistance		20	35	—	k Ω
Output Resistance		—	40	150	Ω
Channel Separation (Stereo)	At $f = 100\text{ Hz}$	—	40	—	dB
	$f = 400\text{ Hz}$	30	45	—	dB
	$f = 10\text{ kHz}$	—	45	—	dB
Channel Balance (Monaural)		—	0.3	1.5	dB
Voltage Gain	At $f = 1\text{ kHz}$	0.5	0.9	1.4	V/V
Pilot Input Level:	19-kHz Input Lamp "ON"	—	15	23	mV RMS
	19-kHz Input Lamp "OFF"	2.0	7.0	—	mV RMS
	Hysteresis Lamp "OFF"	3.0	7.0	—	dB
Capture Range (Deviation from 76-kHz Center Frequency)		± 2.0	± 4.0	± 6.0	%
Total Harmonic Distortion	Multiplex Input Signal = 600 mV RMS (Pilot "OFF")	—	0.4	1.0	%
19-kHz Rejection		25	35	—	dB
38-kHz Rejection		25	45	—	dB
SCA (Storecast) Rejection	Measured Composite Signal: 80% Stereo, 10% Pilot, 10% SCA	—	70	—	dB
Voltage-Controlled Oscillator (VCO) Tuning Resistance	Total Resistance (Term. 15 to 8) required to set $f_{\text{REF}} = 19\text{ kHz} \pm 10\text{ Hz}$ (Term. 11)	21.0	23.3	25.5	k Ω
Voltage-Controlled Oscillator Frequency Drift	$0^\circ \leq T_A \leq 25^\circ\text{C}$	—	+0.1	± 2	%
	$25^\circ \leq T_A \leq 70^\circ\text{C}$	—	-0.4	± 2	%



RESISTANCE VALUES ARE IN OHMS

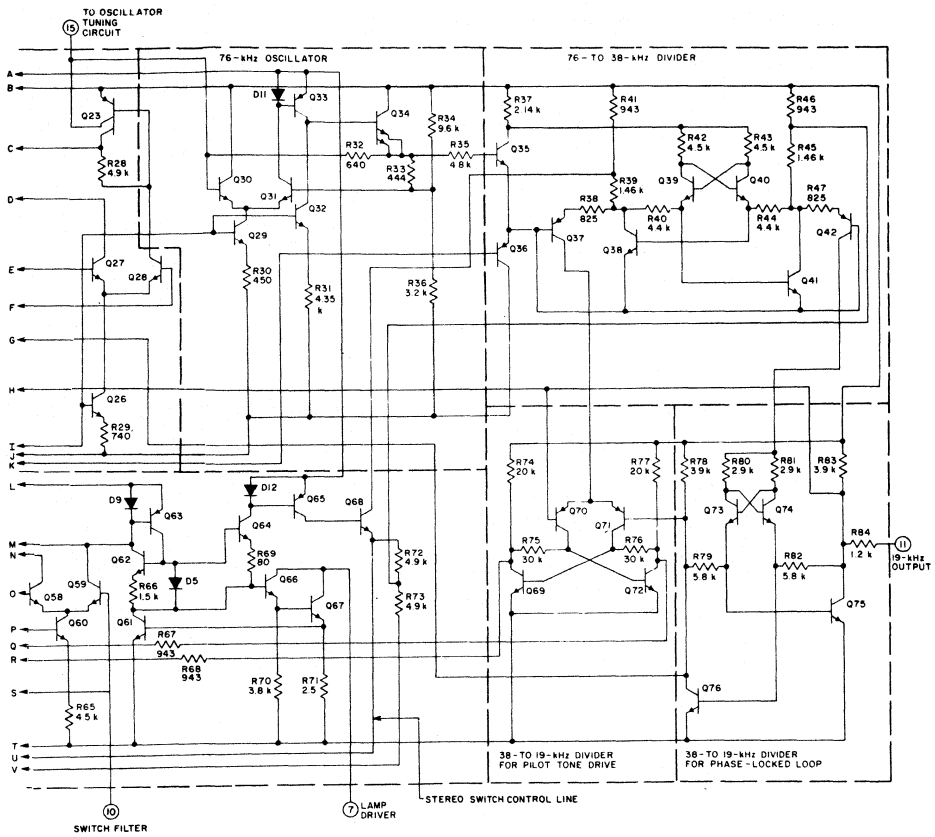
92CL-23177

Fig. 2—Schematic diagram of the CA3195 (cont'd on next page).



92CM-23509

Fig. 3—Test circuit for measurement of dynamic characteristics.



92CL-23177

Fig. 2—Schematic diagram of the CA3195 (cont'd from preceded page).

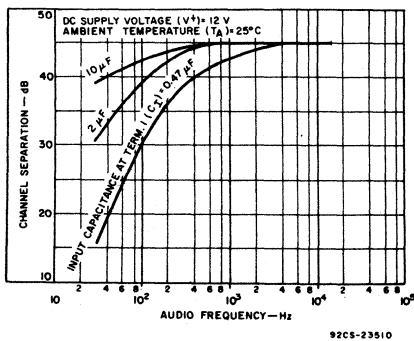


Fig. 4—Channel separation vs. audio frequency.

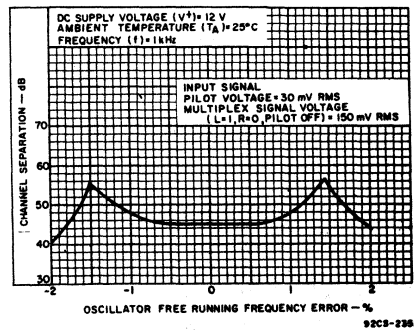


Fig. 5—Channel separation vs. oscillator free running frequency error.

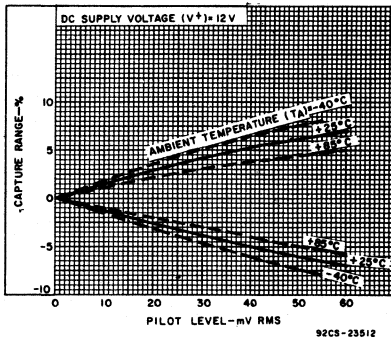


Fig. 6—Capture range vs. pilot level.

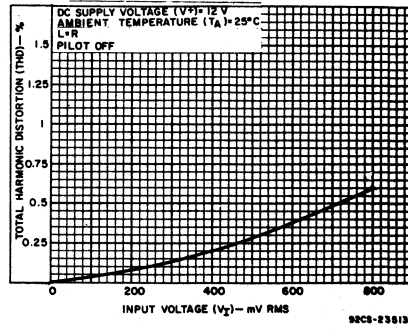


Fig. 7—Total harmonic distortion vs. input level.

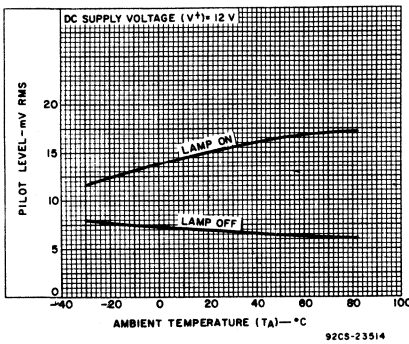


Fig. 8—Lamp turn-on and turn-off sensitivity vs. ambient temperature.

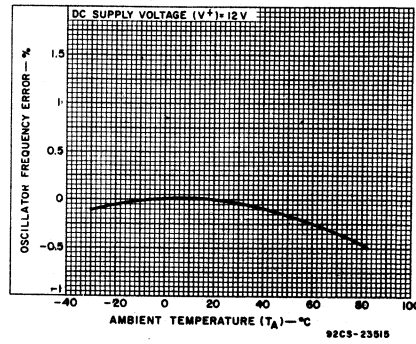
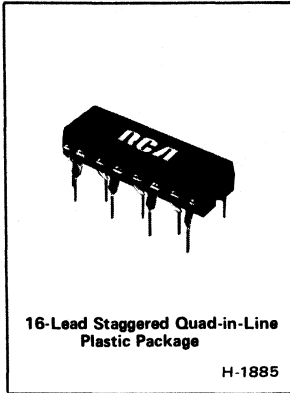


Fig. 9—Oscillator free running frequency error vs. ambient temperature.



TV Synchronous Demodulators

For Color and Black-and-White TV Systems

Features:

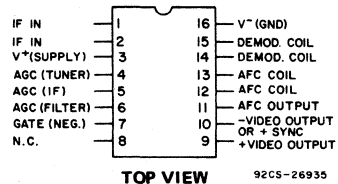
- Synchronous detector with single tuned coil
- Provides rf and if agc (forward)
- Tuner afc available with single quadrature coil
- Dual-polarity noise inverters
- Video amplifier
- Positive- and negative-polarity buffered video
- Differential if input
- Optional use of gating pulse
- Low-voltage, single-polarity power supply

The RCA-CA270AW, CA270BW, and CA270CW are integrated circuits which perform the functions of synchronous detection of the TV if, video amplification and buffering, and noise inversion on dual-polarity waveforms. These devices also offer agc and afc facilities for use with n-p-n transistor if amplifiers and tuners. Both positive and negative polarities of video output are available. This feature provides great flexibility by permitting the designer to use either output for deriving the video and sound channels.

The RCA-CA270 series is pin-compatible and electrically similar to the industry series TCA270, but incorporates several improved features. In particular, improved white noise inversion and sync inversion systems force overshoots in the video waveform to be returned to accurately defined potentials. This design effectively removes dependence on both the degree of overshoot and temperature variations. In addition, reduced current consumption assures lower over-all power dissipation, thereby improving reliability.

The three types are electrically identical in most parameters. The CA270B has the most stringent limits on white level, video inversion, and afc dc offset. The CA270C has the least stringent limits on white level and video inversion, and no afc limits.

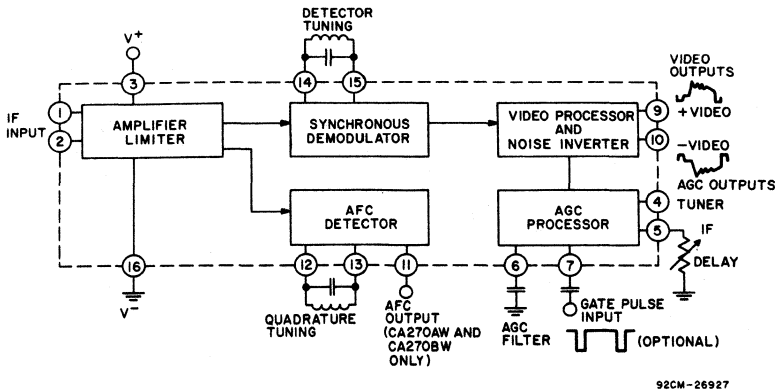
The CA270 series is supplied in a 16-lead staggered quad-in-line plastic package ("W" suffix).



TOP VIEW

92CS-26935

Terminal assignment.



92CM-26927

Fig. 1—Functional block diagram of CA270AW, CA270BW, and CA270CW TV synchronous demodulator.

Linear Integrated Circuits

CA270

MAXIMUM RATINGS,

Absolute-Maximum Values at $T_A = 25^\circ\text{C}$:

DC SUPPLY VOLTAGE (Between Terminals 3 and 16 for 10 s max., with current limited to 100 mA) 18 V

DEVICE DISSIPATION:

Up to $T_A = 55^\circ\text{C}$ 750 mW
Above $T_A = 55^\circ\text{C}$... derate linearly 7.9 mW/ $^\circ\text{C}$

OPERATING TEMPERATURE RANGE

..... -40 to $+55^\circ\text{C}$

STORAGE TEMPERATURE RANGE

..... -65 to $+150^\circ\text{C}$

LEAD TEMPERATURE (During Soldering)

At distance $1/16'' \pm 1/32''$ (1.59 ± 0.79 mm) from case for 10 s max. $+265^\circ\text{C}$

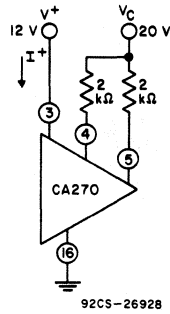


Fig. 2—Supply-current test circuit.

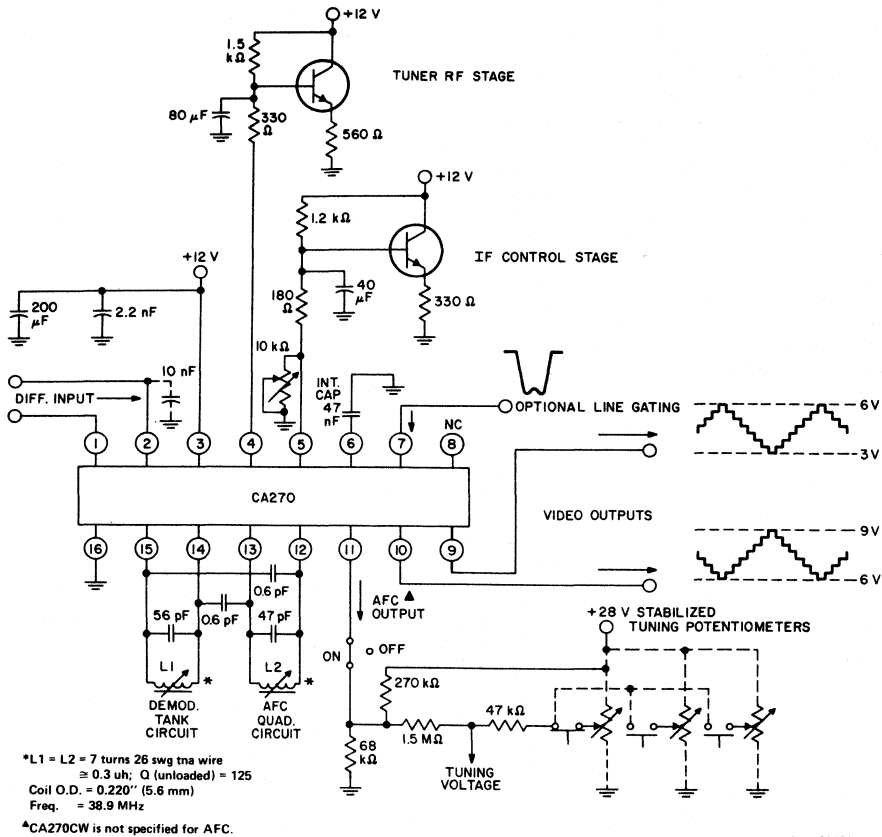


Fig. 3—Typical application circuit for CA270AW and CA270BW.

CA270

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, Supply Voltage (V^+) = 12 V, and Referenced to Test Circuit (Fig. 4).

CHARACTERISTIC	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Supply Voltage, V^+	$V^+ = 12\text{ V}$		10.2	12	13.8	V
Supply Current, I^+ (See Fig. 2)	$V^+ = 12\text{ V}$		22	40	56	mA
Video Characteristics: DC Output Voltage, Term.9 (See Fig. 5)	Zero Signal	CA270AW	5.7	6	6.3	V
		CA270BW	5.8	6	6.2	
		CA270CW	5.5	6	6.5	
DC Output Voltage, Term.10 (See Fig. 5)	Zero Signal	CA270AW	5.6	6	6.4	V
		CA270BW	5.7	6	6.3	
		CA270CW	5.5	6	6.5	
Sync Tip Output Voltage, Term.9	Output=AGC threshold (non-gated)		—	3	—	V
AC Input Voltage, Terms.1,2	Input for output=AGC threshold		50	70	100	mV
Input Res., Term.1			—	3.3	—	$k\Omega$
Input Res., Term.2			—	3.3	—	$k\Omega$
Video Bandwidth, Term.9	At output = -3 dB		—	5	—	MHz
Differential Gain	See Note 1		—	—	10	%
Differential Phase	See Note 1		—	—	10	deg
Intermod. Products: Beat Freq., 1.6 MHz	See Note 1 (95% sat. blue colour bar)		—	—	-60	dB
Beat Freq., 2.8 MHz			—	—	-67	dB
Rejection at Carrier Freq., Terms.9,10,11	F=Video Carrier; V_{IN} for Term.9(dc)=3.7V		-40	—	—	dB
Rejection, Twice Carrier Freq., Terms.9,10,11	F=2X Video Carrier; V_{IN} for Term.9(dc) =3.7 V		-40	—	—	dB
AGC Characteristics: Sat. Voltage, Term.4	Zero Sig.; $I_4 = 10\text{ mA}$		—	—	0.3	V
Sat. Voltage, Term.5	Zero Sig.; $I_5 = 10\text{ mA}$		0.7	—	1.2	V
Breakdown Voltage, Terms. 4,5	I_4 or $I_5 = 1\text{ mA}$ (sink)		14	—	—	V
Control Current, Terms. 4,5			10	—	—	mA
Current Ratio I_4/I_5	$I_5 = 1\text{ mA}$		6	—	—	
Input Signal Increase with resp. to AGC Threshold (See Fig.7)	AGC from threshold to max.		—	—	0.5	dB
AGC Gating Pulse Input, Term. 7 (optional)	Pulse voltage= V^+ to 0; See Note 2		2	—	V^+	V
Input Res., Term.7			—	1.8	—	$k\Omega$
AFC Characteristics: (See Fig. 6) Output Voltage, Term. 11	$f = f_o \pm 0.2\text{ MHz}$	CA270AW	10	—	—	V_{p-p}
		CA270BW	10	—	—	
		CA270CW	—	—	—	
Output Voltage, Term. 11	$f = f_o \pm 1.2\text{ MHz}$	CA270AW	10	—	—	V_{p-p}
		CA270BW	10	—	—	
		CA270CW	—	—	—	
DC Offset Voltage, Term. 11	Zero Sig.; measured across $R_L =$ $50\text{ k}\Omega$ to +6 V		CA270AW -1.7 CA270BW -1 CA270CW —	— — —	1.7 1 —	V

Note 1: CCIR modulation system, peak white = 10% carrier. Note 2: Maximum pulse amplitude must never exceed the supply voltage (V^+).

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CA270

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, Supply Voltage (V^+) = 12 V, (Cont'd)
and Referenced to Test Circuit (Fig. 4).

CHARACTERISTIC	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Noise Inverter Characteristics: Inversion Threshold, Term. 9	Positive noise pulses		—	6.6	—	V
Inversion Threshold, Term. 9	Negative noise pulses		—	2.2	—	V
Noise Inversion Sensitivity, Term. 9	Signal inversion threshold for complete inversion		—	10	—	mV
Video Inversion Characteristics: Video Inversion, Term. 9 (at low carrier levels)	Carrier increase from 0 to 5 mV (appx.8% carrier)	CA270AW CA270BW CA270CW	— — —	— — —	0.2 0.1 0.3	V

APPLICATIONS

The diagram shown in Fig. 3 is typical of the type of circuit used in a practical application of the CA270 series devices.

Video Detector

The if input signal may be applied push-pull to terminals 1 and 2, or single-ended to either terminal 1 as shown, or to terminal 2. These input terminals are internally biased.

The detector tank circuit can be tuned by applying a 50 mV cw signal of video if frequency to the input and adjusting the inductor L1 for maximum differential output between terminals 9 and 10. The input signal is then reduced to 25 mV and L1 is re-adjusted for maximum output.

AFC Detector

The afc quadrature tank circuit should be tuned only after the detector adjustment has been made. Using the same input signal, inductor L2 should be adjusted for 6 V dc output at terminal 11. The 0.5-pF quadrature phase-shift coupling capacitors can affect symmetry and actual values will depend on the layout used. When L1 and L2 are properly tuned, the output swing at terminal 11 will be 10 volts minimum for frequencies of ± 0.2 MHz to ± 1.2 MHz about the if carrier frequency.

AGC Detector

The agc threshold, corresponding to sync tip level, is approximately 3 volts at terminal 9. Full agc potential will be developed if the input signal increases by 0.5 dB maximum with respect to the threshold value. The agc control at terminal 4 is intended for tuner control. The agc control at terminal 5 is for forward agc control of n-p-n transistors in the if amplifier. When sinking 10 mA, the zero-signal agc voltage at terminal 4 is 0.3 volt maximum; at terminal 5, it is 1.2 volts maximum.

The design of the device is such that the sink current at terminal 4 is a minimum of 6 times that at terminal 5. The rf agc sink current begins to decrease when the if sink current is about one-sixth of that required to saturate the rf agc output at terminal 4. The rf agc delay may be adjusted by means of a variable resistor between terminal 5 and ground. This adjustment modifies the if system gain, thus affecting the rf delay threshold. At maximum gain the current into terminal 5 is large compared to the current in the variable resistor and adjustment is ineffective. As the signal increases and rf agc is applied, the terminal 5 sink current approaches zero and the if agc is determined by the value of the variable resistor.

A horizontal gating pulse may be applied to terminal 7 to gate the agc detector. The agc threshold (sync tip) decreases approximately 0.3 volt at terminal 9 when gating is used. The gating pulses must be negative-going with a recommended minimum amplitude of 3 volts. They may be ac or dc coupled, but the maximum peak value must not exceed the dc supply voltage at terminal 3. If dc coupling is used, the potential during fly-back should be less than 0.5 volt and during scan, greater than 1.5 volts.

Noise Inverter

Noise pulses in excess of 6.6 volts at terminal 9, which would result in "white spots", are processed in the device by inverting and clamping them to near black level (approx. 3.6 V). Noise pulses at levels of less than 2.2 volts at terminal 9 which would result in sync noise interference, are inverted and returned to black level.

Complete inversion occurs for signals 10 mV above the inversion threshold.

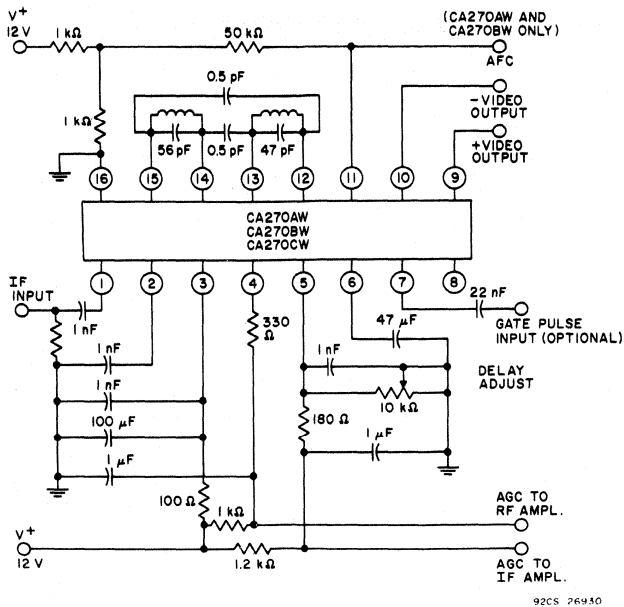


Fig. 4—Test circuit for CA270AW, CA270BW, and CA270CW.

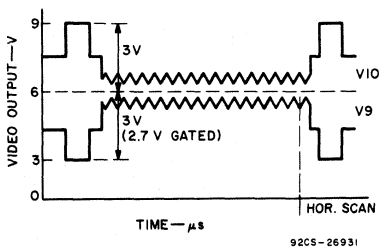


Fig. 5—Typical waveforms for video outputs.

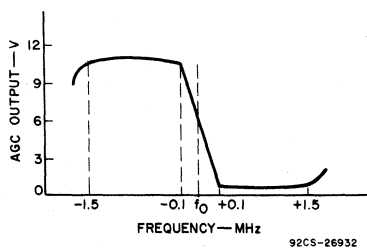


Fig. 6—Typical AFC characteristic.

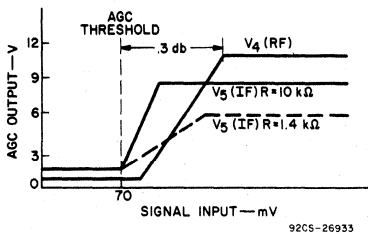


Fig. 7—Typical AGC characteristics.

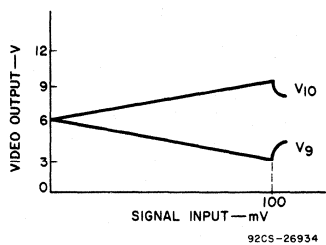
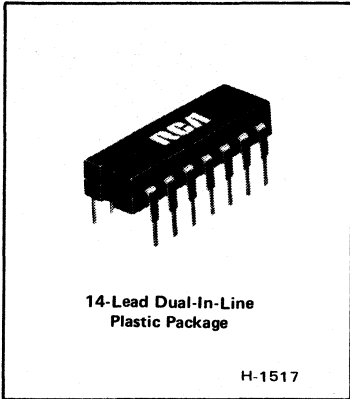


Fig. 8—Typical transfer characteristics.

CA1352E



TV IF Amplifier

With AGC and Keyer Circuit

Features:

- Gain = 52 dB (typ.)
- Gain reduction = 66 dB (min.)
- Gated AGC accepts either positive or negative video
- Adjustable delay for tuner AGC

The RCA-CA1352E is a monolithic integrated circuit designed for use as the if amplifier in color or monochrome TV receivers. It incorporates a high-gain gated-AGC system with a range of 66 dB (min.), and the rf AGC delay may be adjusted externally. Separate inputs are provided for positive and negative video; the gated AGC circuit will accept either, depending on the input terminal used.

The CA1352E is supplied in a 14-lead dual-in-line plastic package, and is directly interchangeable with the industry type 1352 in similar packages.

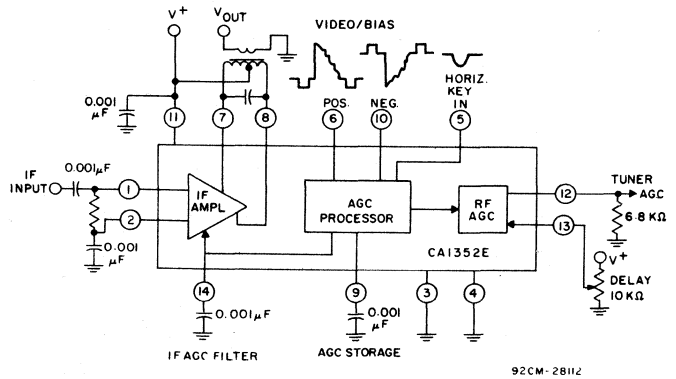


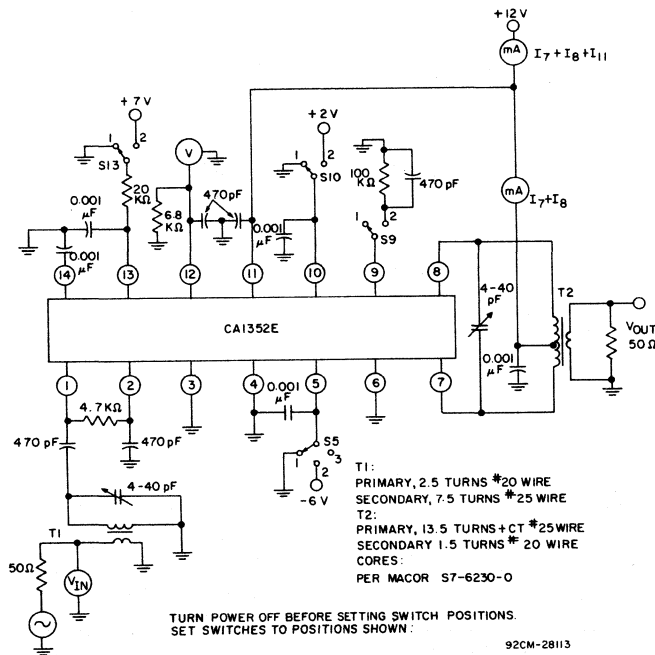
Fig. 1 — Block diagram.

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$:

INPUT VOLTAGE (Terminal 1 or 2)	10 V _{p-p}
AGC INPUT VOLTAGE (Terminal 6 or 10)	6 V
HORIZONTAL KEYING VOLTAGE (Terminal 5)	+10 to -20 VDC
SUPPLY VOLTAGE:	
Between terminals 4 and 11	18 V
Between terminals 7 or 8 and 4	18 V
DEVICE DISSIPATION:	
Up to $T_A = 55^\circ\text{C}$	750 mW
Above $T_A = 55^\circ\text{C}$	derate linearly at 7.9 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE (T_A)	
Operating	-40 to +85 $^\circ\text{C}$
Storage	-65 to +150 $^\circ\text{C}$
LEAD TEMPERATURE (During Soldering):	
At distance 1/16 ± 1/32 in. (1.59 ± 0.79 mm) from case for 10 seconds max.	+265 $^\circ\text{C}$

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V^+ = 12\text{ Vdc}$, $f = 45\text{ MHz}$

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
Power Gain	$V_{IN} = 100\ \mu\text{V}$, see Fig.3	43.5	52	—	dB
AGC Range	See Fig.3	66	—	—	dB
Total Current ($I_7 + I_8 + I_{11}$)	No signal, see Fig.3	19	—	35	mA
Output Stage Current ($I_7 + I_8$)		4.6	—	7.4	mA
Tuner AGC Voltage at Terminal 12	No signal	—	—	0.6	V
	Max. signal	6.5	—	—	
Single-Ended Input Capacitance	$V_{IN} = 30\text{ mV}$ at 45 MHz	—	10	—	pF
Single-Ended Input Resistance		—	0.9	—	k Ω
Single-Ended Output Capacitance	$V_{IN} = 100\text{ mV}$ at 45 MHz	—	2.5	—	pF
Single-Ended Output Resistance	$V_{IN} = 100\text{ mV}$ at 45 MHz	—	20	—	k Ω



CHARACTERISTIC	S5	S9	S10	S13	V _I	MEASURE
Power Gain	1	2	1	1	100 μV	V_{OUT}^1
AGC Range	2	1	2	2	Note 1	V_{OUT}^2
Total Current ($I_7 + I_8 + I_{11}$)	1	1	1	1	No Sig.	$I_7 + I_8 + I_{11}$
Output Stage Current ($I_7 + I_8$)	1	1	1	1	No Sig.	$I_7 + I_8$
Tuner AGC Voltage: At V_{12} Low	3	1	2	2	100 μV	V_{12} Max.
	2	1	2	2	100 μV	V_{12} Min.

Note 1: Increase input signal until $V_{OUT}^2 = V_{OUT}^1$ ($V_I \geq 200\text{ mV}$).

Fig.2 - Test Circuit.

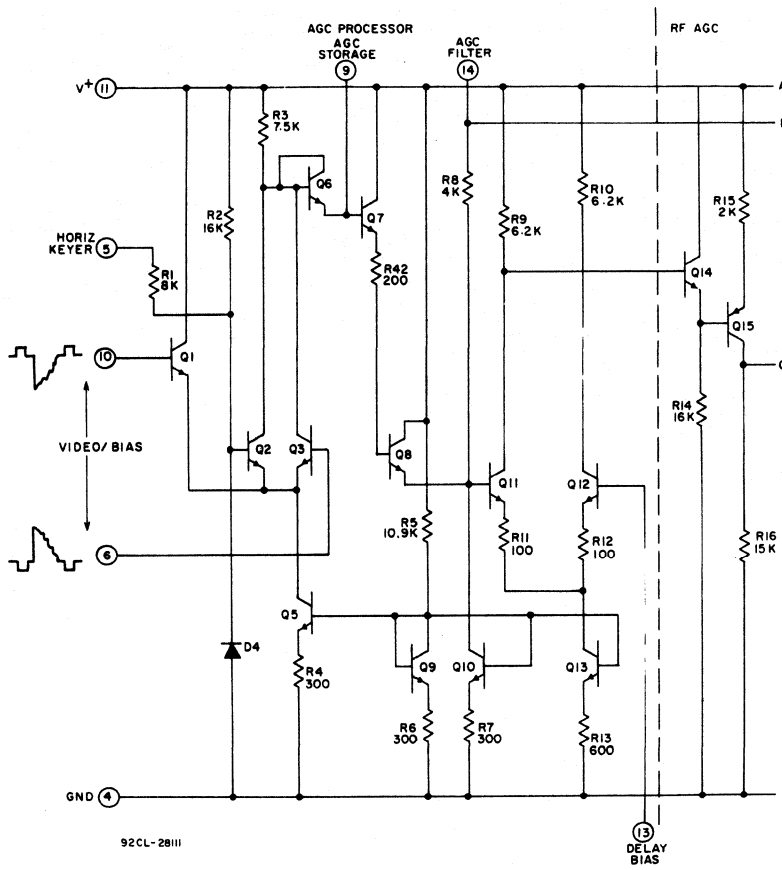


Fig.3 - Schematic diagram.

CIRCUIT DESCRIPTION

As shown in the block diagram, Fig. 1, the CA1352E consists of a high-gain if amplifier (52 dB typ.), an AGC processor which accepts either polarity video signal (approx. 3.5 Vp.p), and an rf AGC amplifier with delay circuit. For proper operation the AGC processor requires three inputs:

- (1) A negative-going keying pulse of approximately 8 Vp.p applied to terminal 5.
- (2) A video signal suitably biased.
 - a) If a white positive video signal is used, it is applied to terminal 6. The sync tip should be biased at +2 V.
 - b) If a white negative video signal is used, it should be applied to terminal 10. The sync tip should be biased to +4.5 V. It is recommended that an additional external resistance of 3.9 kΩ be inserted in series with the key input (terminal 5) when white negative video is used.

- (3) The third input to the processor is a dc bias potential.
 - a) For white positive video signals the bias is applied to terminal 10. The value of the bias is +1 to +4 Vdc, with a nominal value of +2 V.
 - b) For white negative video signals, the bias is applied to terminal 6. The value of the bias is +8 to +1 Vdc, with a nominal value of +4.5 V.

The AGC processor charges the AGC storage capacitor, connected externally to terminal 9, during the keying pulse. The amount of charge is determined by the amplitude of the video signal and the dc bias potential. As shown in the schematic, the current is discharged through Q7. The AGC potential across the external capacitor is applied to the if amplifier and to the AGC delay and control circuits.

The if amplifier consists of a modified cascode-balanced amplifier. The input stages Q21 and Q25 operate at a fixed bias point

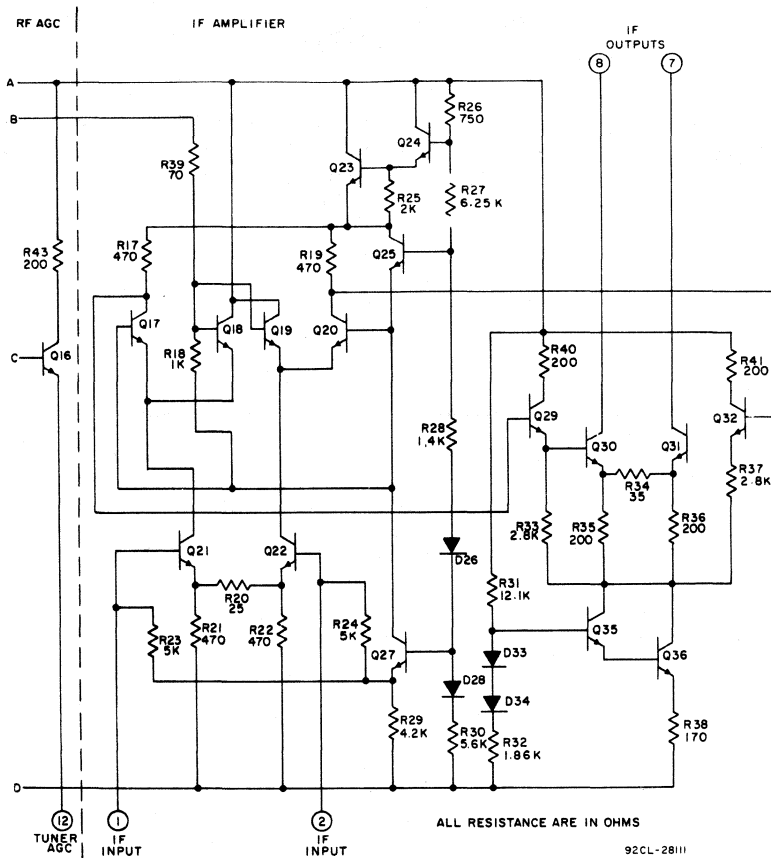


Fig.3 - Schematic diagram.

to reduce the input impedance variations as a function of signal level. At maximum if gain the total collector current of Q21 and Q25 flows through the ac grounded-base transistors Q17 and Q20, respectively. When the signal level at the input increases and the AGC becomes functional, part of the collector currents are diverted to dummy loads Q18 and Q19. The if signal at the collectors of Q17 and Q20 are connected to the balanced output amplifier consisting of Q29 through Q36. The output im-

pedance is held nearly constant because the output stages are operated at a constant current determined by Q36.

The delayed rf AGC voltage at terminal 12 varies from less than 0.6 V with no signal input to greater than 6.5 V at high input-signal conditions.

The tuner AGC threshold point can be changed by the voltage applied to terminal 13. Increasing V13 "delays" the rf AGC so that turn-on occurs with higher input-signal levels.

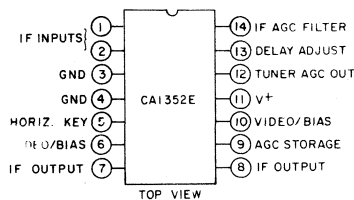
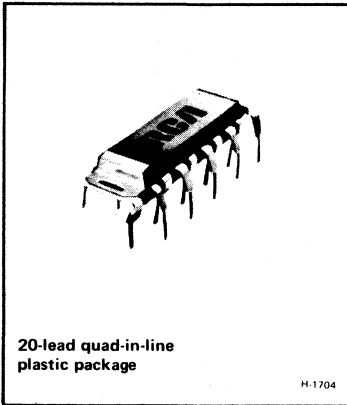


Fig.4 - Terminal assignment.

CA3068



Television Video IF System

FEATURES:

- High-gain wide-band IF amplifier: 75 dB typ. at 45 MHz
- Gain reduction with excellent stability: 50 dB typ. at 45 MHz
- Video detector with linear characteristics
- Video amplifier: 12 dB gain
- Impulse noise limiter
- Keyed AGC with noise immunity circuits
- Delayed AGC for tuner
- Buffered AFT output
- Separate sound IF intercarrier amplification
- Sound carrier detector
- 4.5 MHz sound carrier amplifier
- Isolated zener reference diode for regulated voltage supply

RCA-CA3068* is a monolithic integrated circuit that incorporates an entire video TV-IF subsystem on a single chip. Innovations in integrated circuit design, in addition to the many active devices and closely matched components utilized in the circuit, make the CA3068 ideally suited for use in color and black-and-white TV receivers.

The primary functions performed by the IF subsystem are video IF amplification, linear detection, video output amplification, AGC from a keyed supply, AGC delay for tuner, sound carrier detection, sound carrier amplification, and a buffered AFT output. The advanced circuit design of the CA3068 also includes secondary functions for improved

noise immunity and minimal airplane flutter. An isolated zener reference diode, incorporated in the IC, provides a convenient and economical means for controlling the regulated voltage supply. The inherent wide bandwidth capability (10-70 MHz) and high overall gain (87 dB) make the CA3068 suitable for other AM IF applications whose frequencies range within this bandwidth.

The CA3068 utilizes a unique 20-lead quad-in-line plastic package. This package also includes a wrap-around shield that serves to minimize interlead capacitances.

* Formerly Developmental No. TA5914

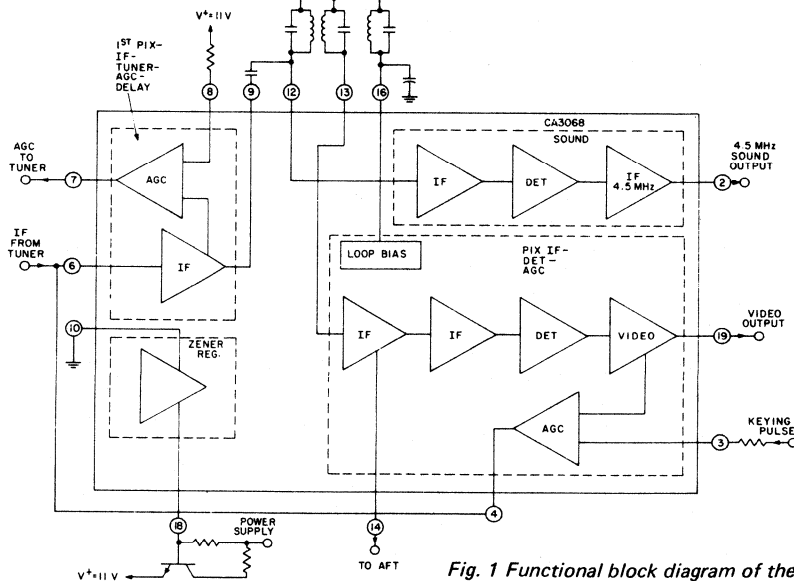


Fig. 1 Functional block diagram of the CA3068.

MAXIMUM RATINGS, Absolute Maximum Values, at $T_A = 25^\circ C$

DC Supply Voltage:

Between Terminals 15 and 5*	11.3	V
Terminal 7 (Collector to ground)	20	V
Terminal 9 (Collector to ground)	20	V
DC Current (into Terminal 18)	2	mA

Device Dissipation:

Up to $T_A = 60^\circ C$	600	mW
Above $T_A = 60^\circ C$	derate linearly 6.7 mW/ $^\circ C$	

Ambient Temperature Range:

Operating	-40 to +85	$^\circ C$
Storage	-65 to +150	$^\circ C$

Lead Temperature (During soldering):

At distance not less than 1/32" (0.79 mm) from case for 10 seconds max.	+265	$^\circ C$
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* This rating does not apply when using the internal zener reference in conjunction with the pass transistor.

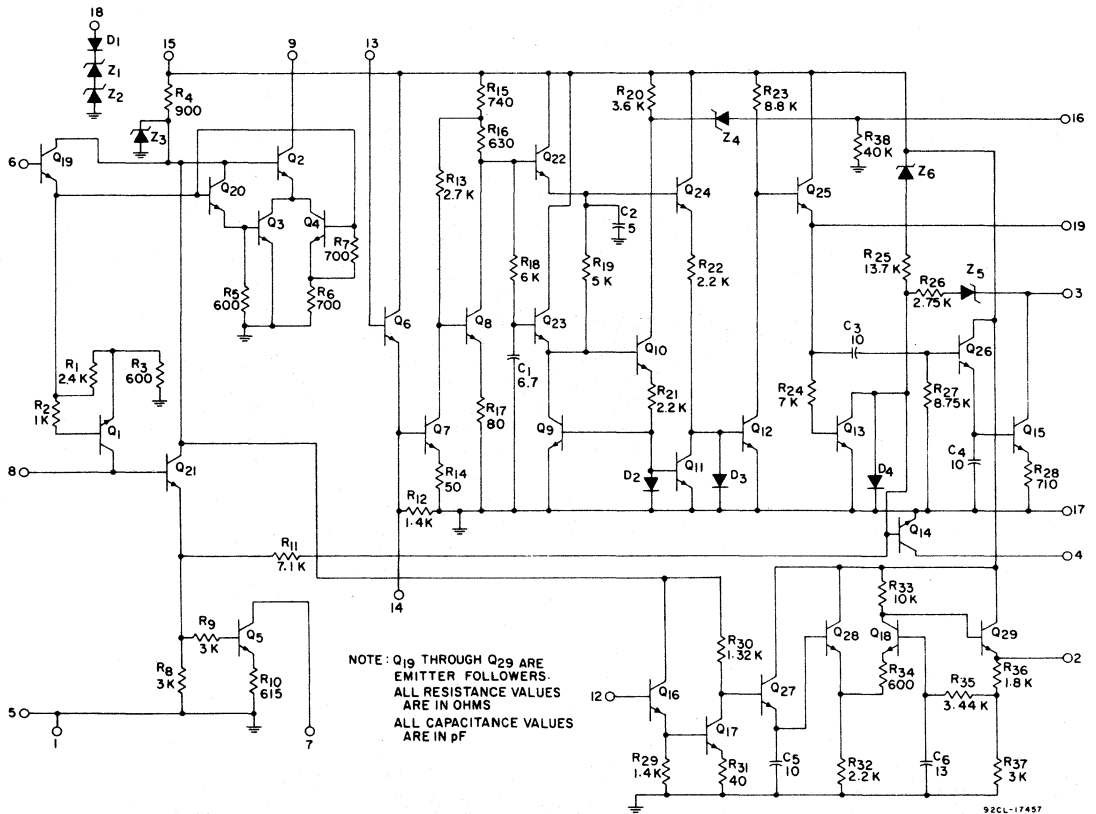


Fig. 2 - Simplified schematic diagram of the CA3068.

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CA3068

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

CHARACTERISTIC	SYMBOL	TEST CONDITIONS		LIMITS			UNITS
			CIRCUIT Fig. No.	Min.	Typ.	Max.	
Static (DC) Characteristics							
Quiescent Circuit Current	I_{15}	—	3	15	—	45	mA
DC Voltages:							
Terminal 2 (Sound)	V_2	—	5	—	6	—	V
Terminal 3 (Keying Input)	V_3	—	3	6.4	—	10	V
Terminal 7 (1) (AGC)	V_7	—	3	16	—	21	V
Terminal 7 (2) (AGC)	V_7	—	4	—	1	—	V
Terminal 8 (AGC Delay)	V_8	—	4	—	4	—	V
Terminal 9 (Cascode Collector)	V_9	—	3	—	8.5	—	V
Terminal 16 (Bias)	V_{16}	—	3	1.1	—	2.3	V
Terminal 18 (Zener)	V_{18}	$V_5 = V_{17} = 0\text{ V}, I_{18} = 1\text{ mA}$	—	10.6	11.9	13.2	V
Terminal 19 (White Level)	V_{19}	—	5	6	—	10	V
Dynamic Characteristics							
Video Sensitivity	e_1	$f_o = 45.75\text{ MHz, Mod. (AM)} = 85\%$ at 400 Hz; Adjust e_1 for 4 V_{p-p} at Term. 19	6	40	100	200	μV
Sync. Tip Level Voltage	V_{19}	$f_o = 45.75\text{ MHz, } e_1(\text{CW}) = 10\text{ mV}$	6	0.4	0.8	1.6	V
Automatic Fine Tuning (AFT) Drive Level Voltage	V_{14}		6	—	15	—	mV
Delay Bias Voltage: At $e_1 = 10\text{ mV}$	V_7	$f_o = 45.75\text{ MHz, } e_1(\text{CW}) = 20\text{ mV};$ Adjust R_1 for $V_7 = 14\text{ V}$	6	16	—	—	V
At $e_1 = 30\text{ mV}$				0.5	—	2	V
3.58 MHz Chroma Output Voltage	V_{19}	$f_o = 45.75\text{ MHz, } e_1(\text{step mod.}) =$ 10 mV; $f_1 = 42.17\text{ MHz, } e_1(\text{step mod.}) =$ 3.33 mV	6	0.5	0.8	—	V
4.5-MHz Sound Output Voltage	V_2	$f_o = 45.75\text{ MHz, } e_1(\text{step mod.}) =$ 10 mV; $f_2 = 41.25\text{ MHz, } e_1(\text{step mod.}) =$ 2.5 mV	6	50	200	—	mV
Parallel Input Impedance: Resistance at Term. 6 Capacitance at Term. 6	R_{1-6} C_{1-6}	$f_o = 45.75\text{ MHz}$ Impedance and Admittance measured at bias conditions as developed by circuit shown in Fig. 7	7	4	—	—	k Ω pF
Resistance at Term. 12	R_{1-12}		7	—	4.5	—	k Ω
Capacitance at Term. 12	C_{1-12}		—	—	4	—	pF
Resistance at Term. 13 Capacitance at Term. 13	R_{1-13} C_{1-13}		7	—	5	—	k Ω pF
Parallel Output Impedance: Resistance at Term. 9 Capacitance at Term. 9	R_{O-9} C_{O-9}		7	30	—	—	k Ω pF
Cascode Transfer Characteristics: Magnitude of Forward Transadmittance	$ y_f $		7	—	50	—	mmho
Reverse Transfer Capacitance	C_r		7	—	0.001	—	pF

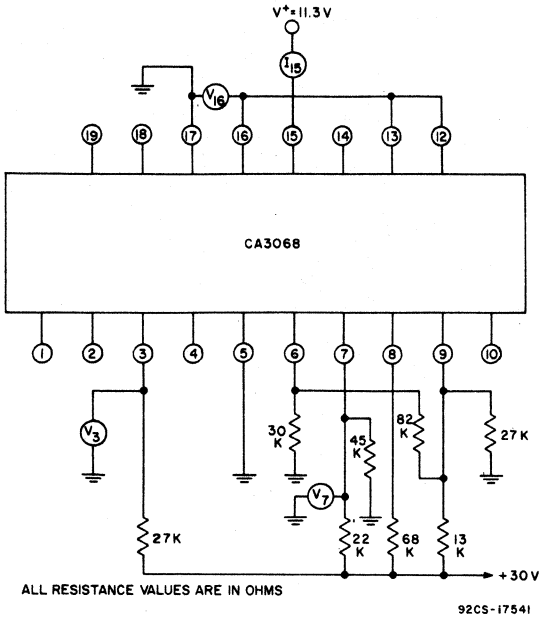


Fig. 3 — Test circuit for measurement of quiescent current (I_{15}), keying terminal voltage (V_3), bias voltage (V_{16}), AGC terminal voltage 1 (V_7), and cascode collector voltage (V_9)

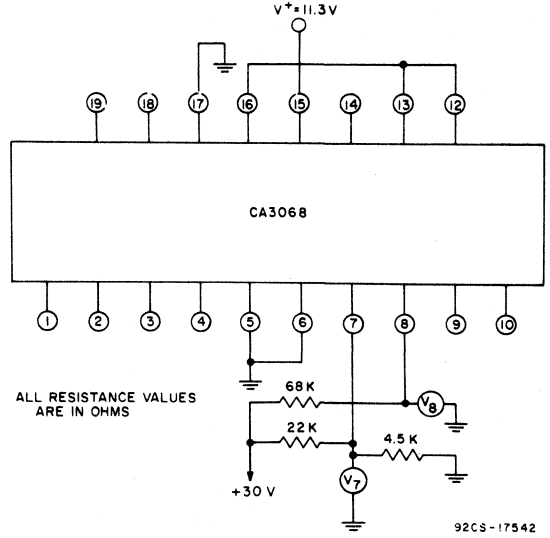


Fig. 4 — Test circuit for measurement of AGC terminal voltage 2 (V_7) and terminal 8 voltage (V_8).

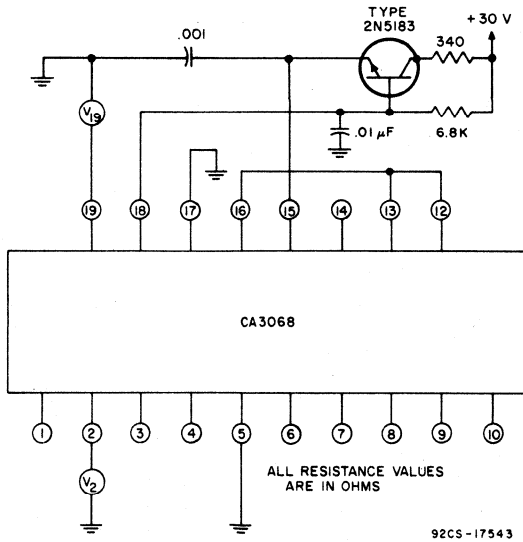
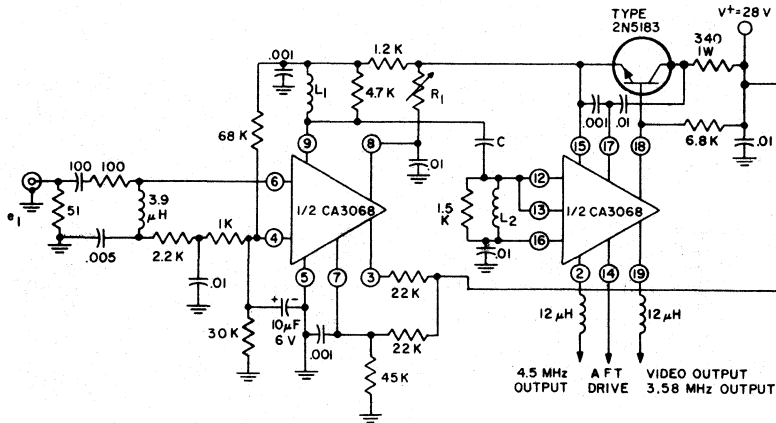


Fig. 5 — Test circuit for measurement of white level (V_{19}) and terminal 2 voltage (V_2).

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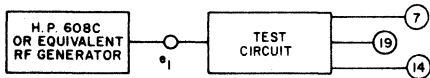
CA3068



$R_1 = 50 \text{ K}\Omega$ POTENTIOMETER
 $L_1 = 2.2 \mu\text{H}$: ADJUST No. OF TURNS FOR ALIGNMENT
 $L_2 = 1.5 \mu\text{H}$: ADJUST No. OF TURNS FOR ALIGNMENT
 $C \cong 1 \text{ pF}$: ADJUST FOR PROPER ALIGNMENT

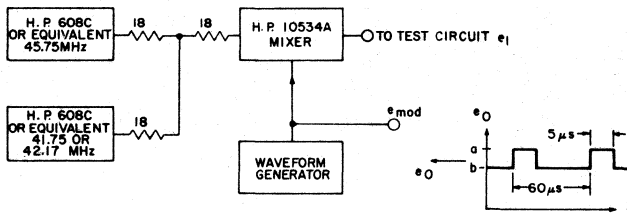
ALL RESISTANCE VALUES ARE IN OHMS

UNLESS OTHERWISE INDICATED, ALL CAPACITANCE VALUES:
 LESS THAN 1.0 ARE IN MICROFARADS
 1.0 OR GREATER ARE IN PICOFARADS



92CS-17537R1

(a) Test setup for measurement of video sensitivity, sync. tip level, delay bias, AFT drive voltage.



ALL RESISTANCE VALUES ARE IN OHMS

- 1- ADJUST LEVEL "a" TO GIVE 6dB ATTENUATION OF MIXER
- 2- ADJUST LEVEL "b" SO THAT THE STEP (a-b) AT VIDEO OUTPUT TERM. IS 3 VOLTS. APPLY ONLY 45.75 MHz TO ADJUST STEP WAVEFORM.

92CS-17538

(b) Test setup for measurement of sound and chroma outputs.

Fig. 6 - Typical dynamic test circuit diagrams.

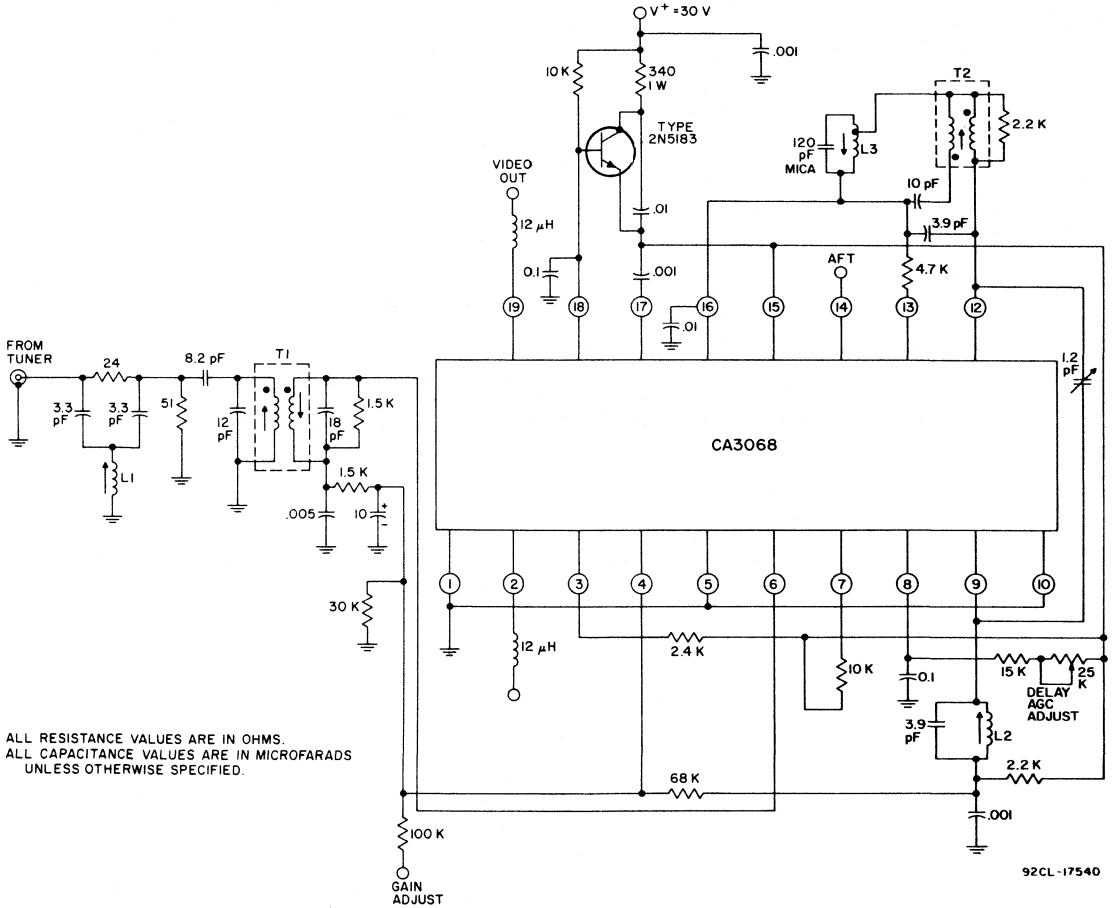
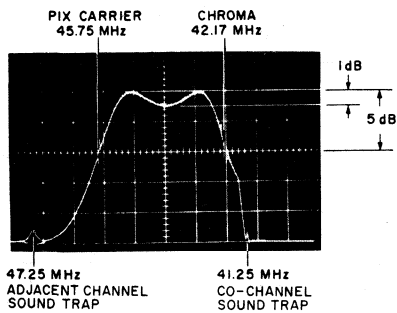


Fig. 7a – Color TV-IF amplifier test circuit.

Alignment of the IF Amplifier

1. Apply a 2 to 4 mV signal from a sweep generator, Telonic SV13 or equivalent to the input of the IF amplifier.
2. Apply a negative DC supply voltage, to the Gain Adjust Terminal.
3. Set the gain supply voltage to provide a peak-to-peak output of 6 volts.
4. The overall response curve should conform to the waveform shown in Fig. 7b.



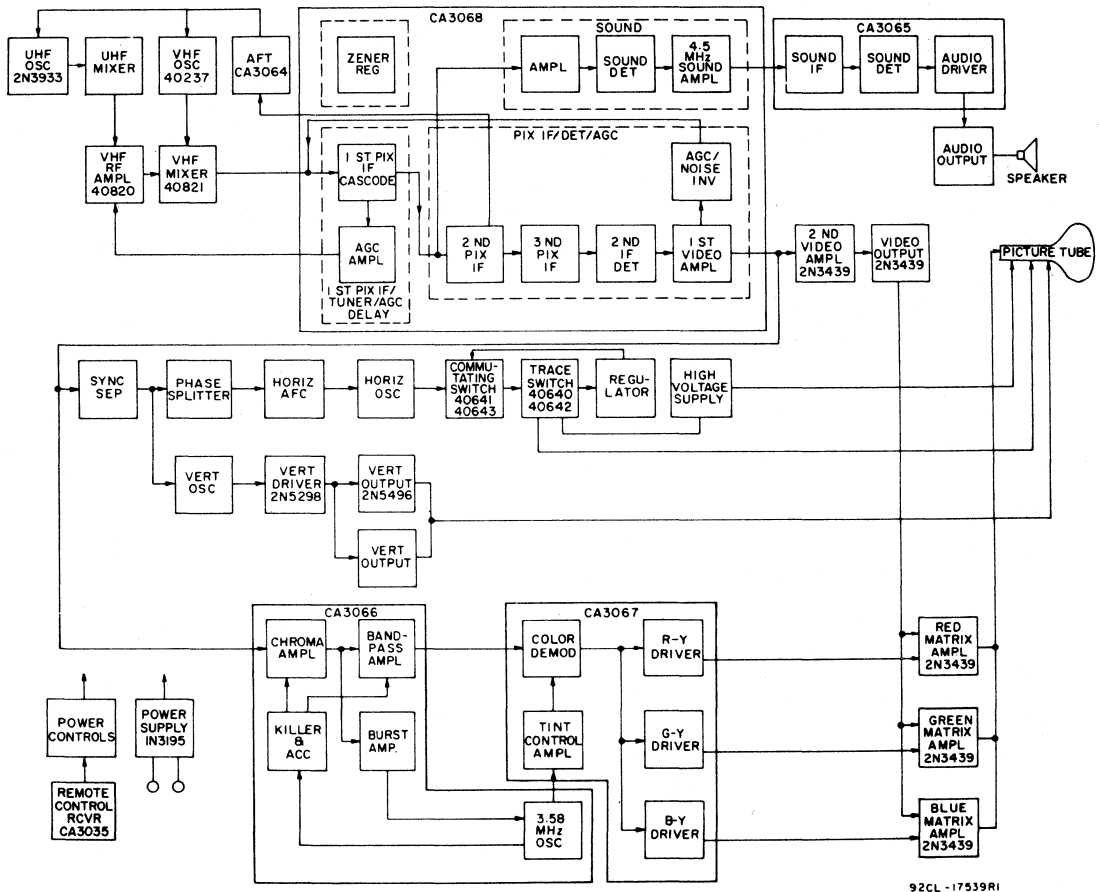
92CS-17549

Fig. 7b – Color TV-IF amplifier with associated waveform and test circuit.

Linear Integrated Circuits

CA3068

A TYPICAL COLOR-TV VIDEO SYSTEM



92CL -17539R1

Fig. 8 - Block diagram of a typical color TV receiver utilizing the CA3068.

Application Information

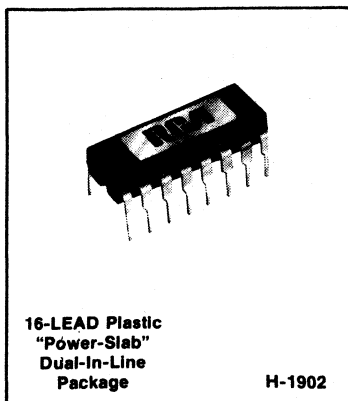
A block diagram of a typical color TV application of the CA3068 is shown in Fig. 8. The input from the TV tuner is applied to the IF cascode amplifier of the IC. The cascode amplifier has a gain reduction of 50 dB typ. and a gain of 35 dB typ. The cascode output is coupled to succeeding stages via the IC lead interconnections. Associated with the cascode amplifier is an AGC delay network that provides gain control for the RF amplifier. This arrangement enables the circuit designer to introduce the desired bandpass-shaping circuitry between the cascode input stages and the remaining IF stages. These IF stages provide an additional gain of 40 dB typ. The output, taken from the emitter of the second IF stage, also provides a buffered AFT signal that is designed to drive the RCA-CA3064 TV Automatic Fine-Tuning IC.

The IF detector circuit provides an extremely linear output signal that is DC coupled to the first video amplifier. The first video amplifier has a voltage gain of 12 dB typ. The detector and video amplifier circuits provide a signal which

has in addition to its linear output an extremely sharp limiting characteristic. The maximum video output level is approximately 7 volts peak-to-peak. The sharp limiting action of this circuit clips any signal (e.g. impulse noise) that exceeds this 7-volt value.

The video amplifier also provides a signal which drives a keyed AGC signal. The unique keyed AGC circuits utilize active devices that virtually eliminate noise from interfering with the action of the AGC. A separate sound section provides amplification at intercarrier frequencies, sound carrier detection, and sound carrier amplification. This sound section is designed to drive the RCA-CA3065 TV Sound System IC.

A color IF circuit with associated performance data is shown in Fig. 7. For a more detailed description of the CA3068 and related performance and IF printed circuit construction information, refer to the RCA Application Note AN-4544.



16-LEAD Plastic
"Power-Slab"
Dual-In-Line
Package

H-1902

TV Video IF Phase-Locked-Loop Synchronous Detector for Color TV Receivers

FEATURES:

- PLL carrier oscillator with wide pull-in and hold-in range
- Excellent low-level detector linearity
- Noise inversion at video output
- Wide range, variable zero-carrier level adjustment
- Automatic Fine Tuning (AFT) Detector
- Separate output for sound take-off
- 12-volt power supply

The RCA-CA3136P is a linear IC synchronous detector employing a phase-locked oscillator to demodulate the 45.75-MHz video IF signals in color-TV receivers. The CA3136P features AFT voltage for dc control of the tuner; an adjustment for the zero-carrier dc level at the video output terminal; an amplifier arrangement for inverting noise impulses toward the black level; and a separate output terminal (non-inverting) for the sound IF.

The CA3136P is supplied in a 16-lead plastic "power-slab" dual-in-line package.

The "power slab" package has an inherently low junction-to-case (slab) thermal resistance and lends itself to a wide variety of heat-sink methods, depending on the application requirements.

MAXIMUM RATINGS, Absolute-Maximum Values:

Power Supply Voltage	15 V
Power Supply Current	100 mA
Input Signal Voltage	1 Vrms
Device Dissipation:	
Up to $T_A = 45^\circ\text{C}$	1.4 W
Above $T_A = 45^\circ\text{C}$	derate linearly at 13.3 mW/ $^\circ\text{C}$
Thermal Resistance:	
$R_{\theta JA}$ (Junction to Ambient)	75 $^\circ\text{C/W}$
Ambient Temperature Range:	
Operating	-40 to +85 $^\circ\text{C}$
Storage	-65 to +150 $^\circ\text{C}$
Lead Temperature (During Soldering):	
At a distance 1/16 in. \pm 1/32 in. (1.59 \pm 0.79 mm) from case	
for 10 seconds max.	265 $^\circ\text{C}$

CA3136P

SUGGESTED GENERAL ALIGNMENT PROCEDURE

Fig. 1 shows a block diagram of the CA3136 in a typical circuit indicating the internal functions as well as the external circuitry and signals. A 45.75 MHz, 100-mVrms (50-ohm) signal is applied to the VIDEO IF INPUT (Terminal 4). While monitoring the VIDEO OUTPUT (Terminal 10), make the following adjustments in the indicated sequence; (1) adjust the VCO TUNING coil for a dc voltage at the AFT OUTPUT (Terminal 12). (2) Adjust the LIMITER TUNING coil for a minimum dc voltage on Terminal 10. (3) Adjust the VCO

TUNING coil for 5.2 Vdc on Terminal 5 (with 12 volt supply on Terminal 8). (4) Close the AFT DEFEAT switch and note the dc voltage at the AFT OUTPUT (Terminal 12). (5) Return the AFT DEFEAT switch to its open position, and adjust the AFT TUNING coil for the same dc voltage noted when the AFT DEFEAT switch was closed. (6) Remove the rf input and adjust the ZERO CARRIER BIAS potentiometer for 7 volts dc on the VIDEO OUTPUT (Terminal 10). This final adjustment completes the alignment procedure.

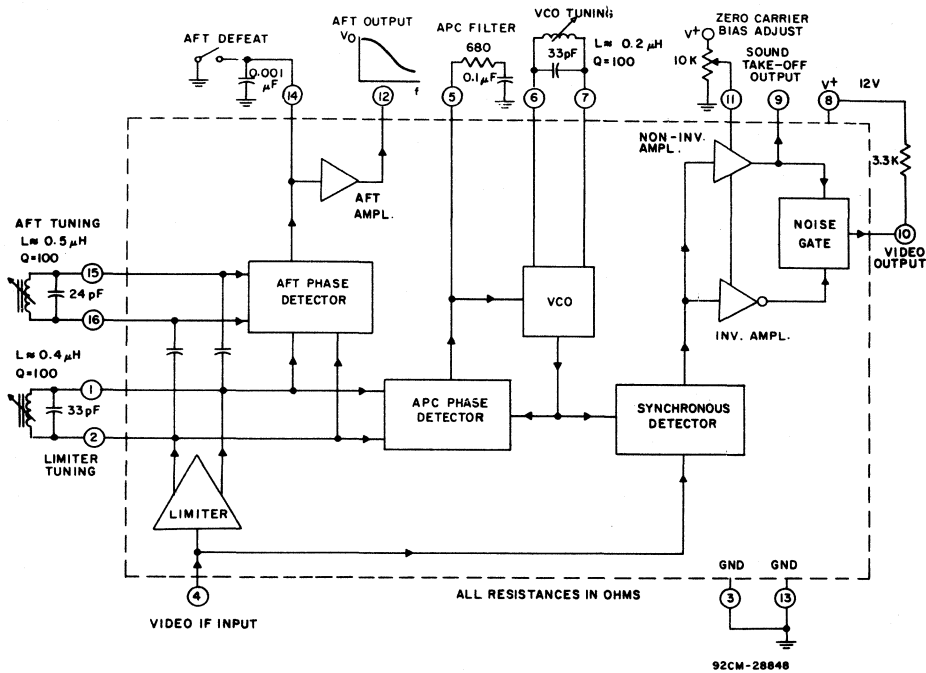


Fig. 1 - Block diagram of the CA3136 in a typical circuit application.

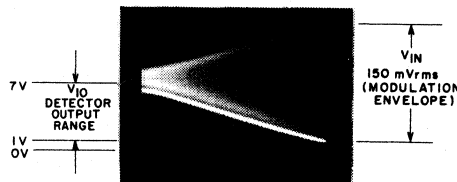


Fig. 2 - Typical detector output linearity.

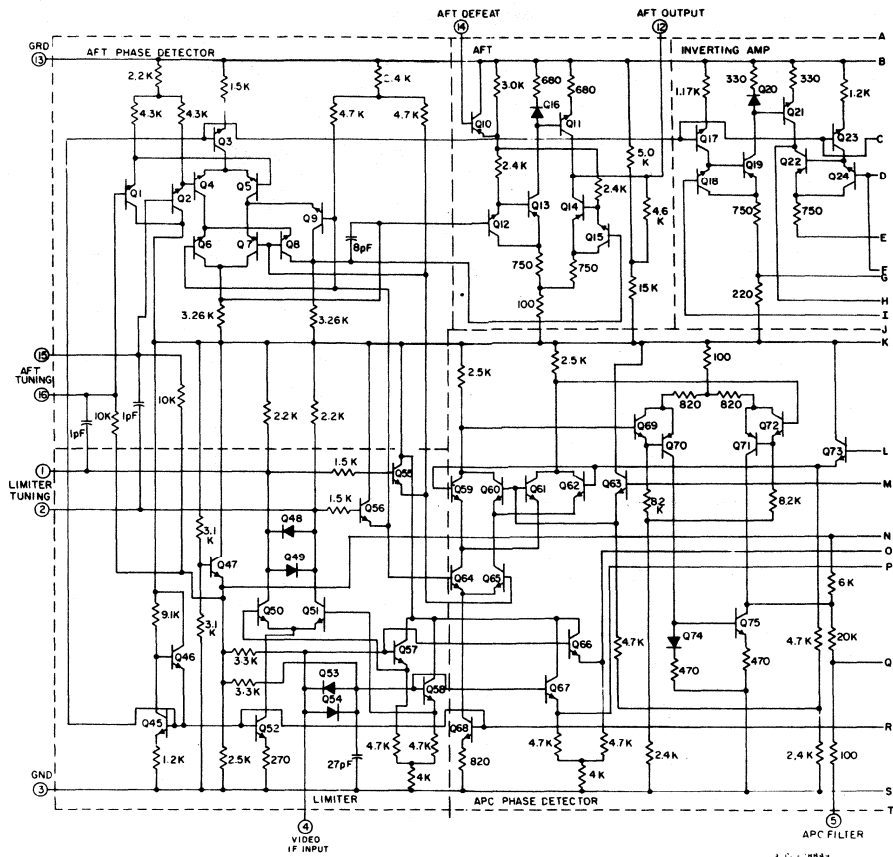
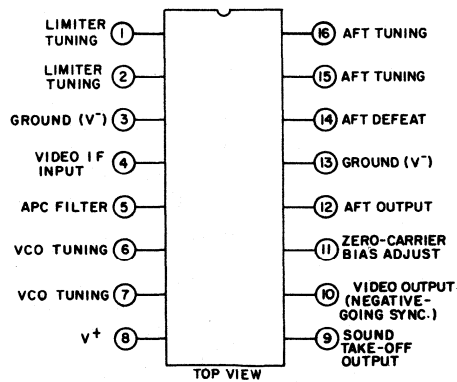


Fig. 3 - Schematic diagram (cont'd on next page).



92CS-28045R1

TERMINAL DIAGRAM

Linear Integrated Circuits

CA3136P

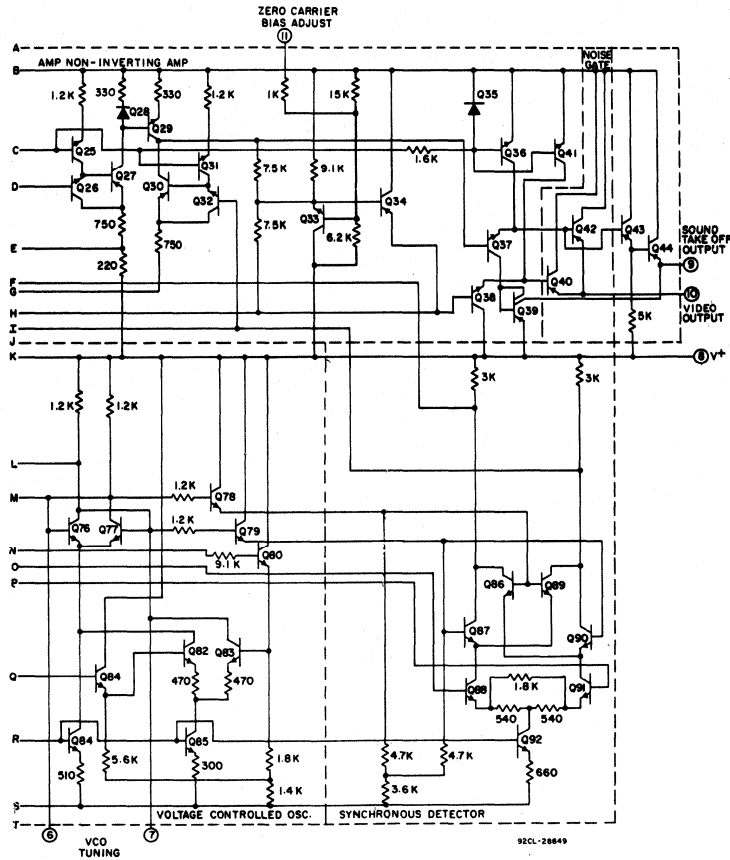


Fig. 3 - Schematic diagram (cont'd from previous page).

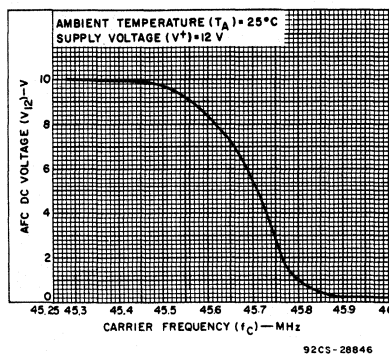


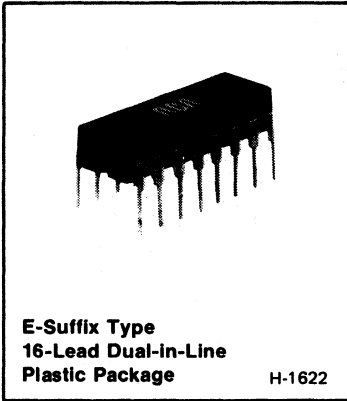
Fig. 4 - Typical AFC output of CA3136P.

TYPICAL ELECTRICAL CHARACTERISTICS

At $V^+ = 12$ VDC, $f_c = 45$ MHz, $T_A = 25^\circ$ C

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	VALUE			UNITS
			Min.	Typ.	Max.	
Supply Current	$I_B + I_{10}$			60	80	mA
Video-Output Voltage	V_{10}	Zero Carrier Bias Adjust		7		V _{DC}
Noise-Inversion Offset Voltage	V_{10}	Referenced to Zero-Carrier Level	-0.2	0.3	+0.8	V _{DC}
Sound IF-Take-Off Output Voltage	V_9	$V_{10} = 7$ V _{DC}		7.7		V _{DC}
AFT Output Voltage	V_{12}	AFT Defeat Switch Closed	2.4	3	3.6	V _{DC}
Oscillator Pull-In Range				3		MHz
Oscillator Hold-In Range				6		MHz
Detector Conversion Gain			26	30		dB
Video Bandwidth				9		MHz
Carrier Rejection at Video Output:						
$f_c = 45$ MHz				30		dB
$2 f_c = 90$ MHz				40		dB
Video IF						
Parallel Input Impedance:						
Resistance at Term. 4	R_p			4		k Ω
Capacitance at Term. 4	C_p			5		pF
Sound Take-Off Output						
Resistance at Term. 9	R_o	1 MHz		50		Ω
Video Output Resistance at Term. 10	R_o	1 MHz		50		Ω

CA3153E



E-Suffix Type
16-Lead Dual-in-Line
Plastic Package H-1622

**Television Video
 IF System**

FEATURES:

- Improved agc
- Fast response
- Sample and hold keyed
- High gain wideband IF amplifiers
- Delayed agc output for tuner
- Gain reduction with excellent stability
- Linear video detector
- Video amplifier
- Low noise
- Internal shunt regulator
- For color or monochrome

The RCA-CA3153E is a monolithic integrated circuit designed to perform IF amplification, video detection, and video-amplifier functions in color and monochrome TV receivers. The signal-to-noise performance has been improved compared to the RCA-CA3068*. The AGC

performance has also been improved through the use of a sample and hold keyed system. The RCA-CA3153E is designed to interface with the RCA-CA3139# Automatic Fine Tuning (aft) circuit, and intercarrier amplifier.

* The CA3068 is described in RCA data bulletin File No. 467.

The CA3139 is described in RCA data bulletin File No. 905.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE:	
Between Terms. 15 and 4	16 V
Between 470Ω connected to Term 12 and 14	35 V
DC SUPPLY CURRENT:	
At Term. 15	20 mA
At Term. 12	30 mA
DEVICE DISSIPATION:	
Up to T _A = +55°C	750 mW
Above T _A = +55°C	Derate linearly at 7.9 mW/°C
AMBIENT TEMPERATURE RANGE:	
Operating	-40 to +85°C
Storage	-65 to +150°C
LEAD TEMPERATURE (During Soldering):	
At distance 1/16 ± 1/32 inch (1.59 ± 0.79 mm) from case for 10 seconds max	+265°C

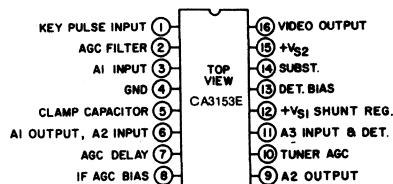
ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

CHARACTERISTIC	TEST CONDITIONS	LIMITS		UNITS
		Min.	Max.	
Operating Supply Voltage, V_{15}	See Note 1	12	14.2	V
Supply Current, I_{15}		3	15	mA
Shunt Regulator Voltage, V_{12}		10.9	13	V
Shunt Regulator Current, I_{12}	$V_{12} = 10.5\text{ V}$	6	20	mA
Tuner AGC High Voltage, V_{10}		18.5	21	V
Tuner AGC Low Voltage, V_{10}		0.3	1.3	V
AGC Current, I_2	Non-Keyed	80	500	μA
AGC Current (Peak), I_2	Keyed Source Current	0.7	3	mA
AGC Current (Peak), I_2	Keyed Sink Current	150	680	μA
Horizontal Key Input	Through $100\text{ k}\Omega$ connected to Term. 1	25	35	V
Video Output High Voltage, V_{16}	At Zero Carrier	7	10	V
Video Output Low Voltage, V_{16}	At 30 mV Input	0.9	2	V
Sensitivity Voltage, V_{16}	At $400\text{ }\mu\text{V}$ Input	0.9	5	V
Noise		—	12	mV (RMS)
Chroma	45.75 MHz , 10 mV ; 42.17 MHz , 3 mV	0.7	1.6	V (RMS)
AFT Drive		35	85	mV (RMS)
Distortion	50 kHz , 80% Modulated, Sync TIP Equiv. 30 mV (RMS)	—	10	%
Delay Voltage	Through $15\text{ k}\Omega$ connected to Term. 7. See note 2	0	V_{15}	V

Note 1: V_{15} MIN. should be at least 0.6 V above Terminal 12 potential. Lower voltage may cause some "white" compression.

Note 2: Zero voltage corresponds to maximum delay at signal input = 30 mV (RMS).

TERMINAL DIAGRAM



92CS-31062

Linear Integrated Circuits

CA3153E

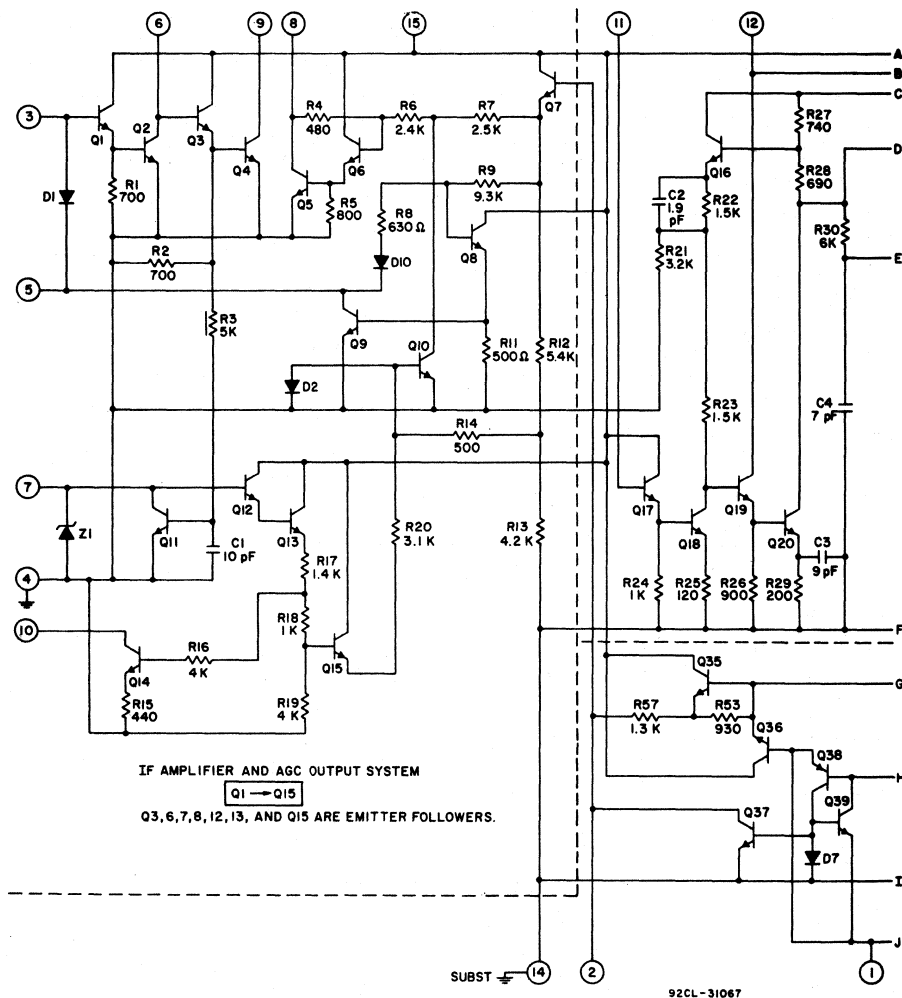


Fig. 1 — Schematic diagram for the CA3153E (cont'd on next page).

THIRD IF-AMPLIFIER STAGE, DETECTOR,
AND VIDEO-AMPLIFIER SYSTEMS

Q16 → Q31

Q16, 17, 19, 21, 22, 25, 27, 30, AND Q31 ARE EMITTER FOLLOWERS

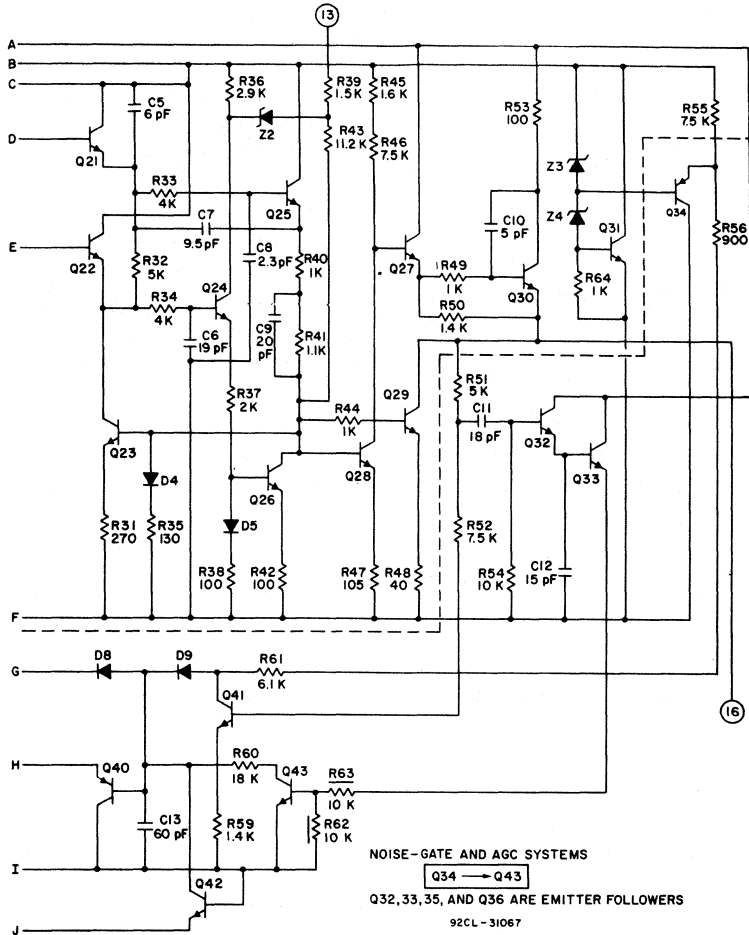


Fig. 1 — Schematic diagram for the CA3153E (cont'd from previous page).

CA3153E

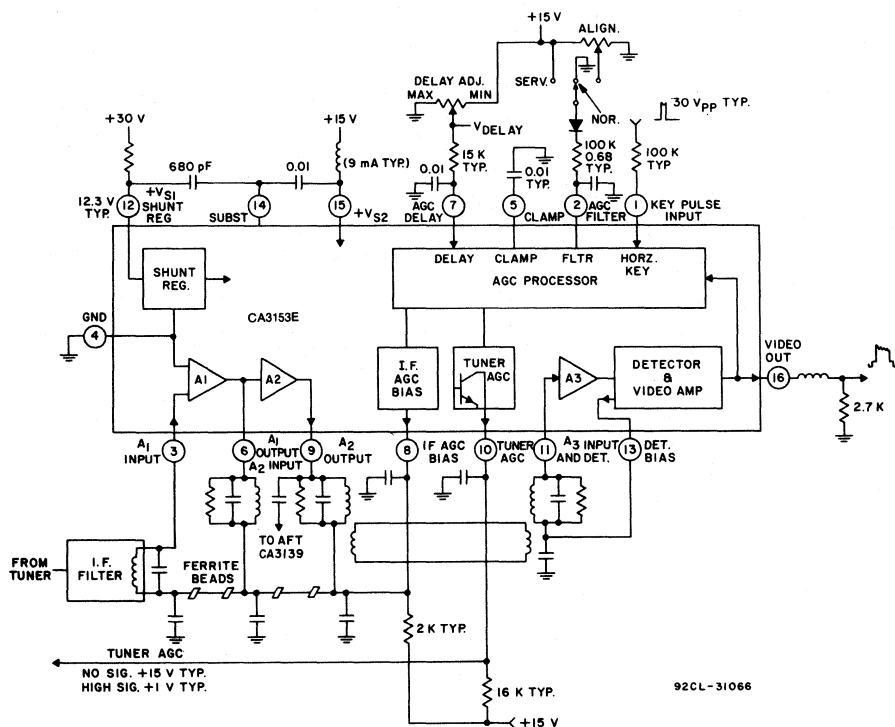


Fig. 2 - Functional block diagram of the IF amplifier-system of CA3153E with typical peripheral circuitry.

AGC System (See Fig. 3)

The AGC system employs a sample-and-hold system to allow a fast-acting agc and reduce the effect of the vertical synchronizing signal on the video output stage. An override path is provided to allow a lower-gain agc system when the key pulse is not locked to the sync signal (for example, during channel selection).

The negative-going sync signal at the video output, Terminal 16, is applied to transistor Q41 through resistors R51 and R52 which act as current-limiting and filtering components. The sync signal is inverted and amplified by transistor Q41. The video portion of the signal is cutoff by the saturation voltage of Q41. When the TV system is in synchronization, the positive sync pulse at the collector of Q41 is coincident with the key input at Terminal 1, Transistor Q42 is turned off by the key pulse. Capacitor C13 is charged by the positive sync pulse through diode D9. The amplitude of the potential at C13 is proportional to the video-signal amplitude. The voltage is transferred through transistors Q40,

Q38, Q36, and Q35 to resistor R57 to form the charge current for the external agc filter capacitor at Terminal 2.

A constant-current discharge path for the capacitor at Terminal 2 is provided by current mirror components D7 and Q37 during the key-pulse duration. Thus the external agc filter capacitor is charged or discharged during the key-pulse interval only by the difference in current between the charge- and discharge currents. At the end of the key-pulse duration, C13 is discharged, and the charge and discharge current paths at Terminal 2 are turned off. Diode D8 provides a lower-gain agc path for turn-on during channel acquisition.

Noise-Gate System (See Fig. 3)

The circuit components, C11, R54, Q32, Q33, and Q43 perform the function of a statistical system to reduce agc gain during "spike" noise. The noise gate turns on for large amplitude fast signals and reduces the agc loop gain.

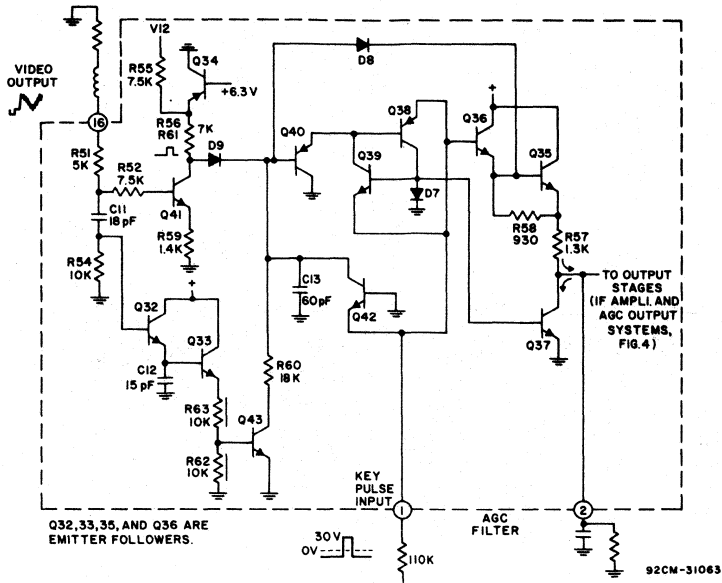


Fig. 3 — Noise-gate and AGC system of CA3153E (Q34—Q43).

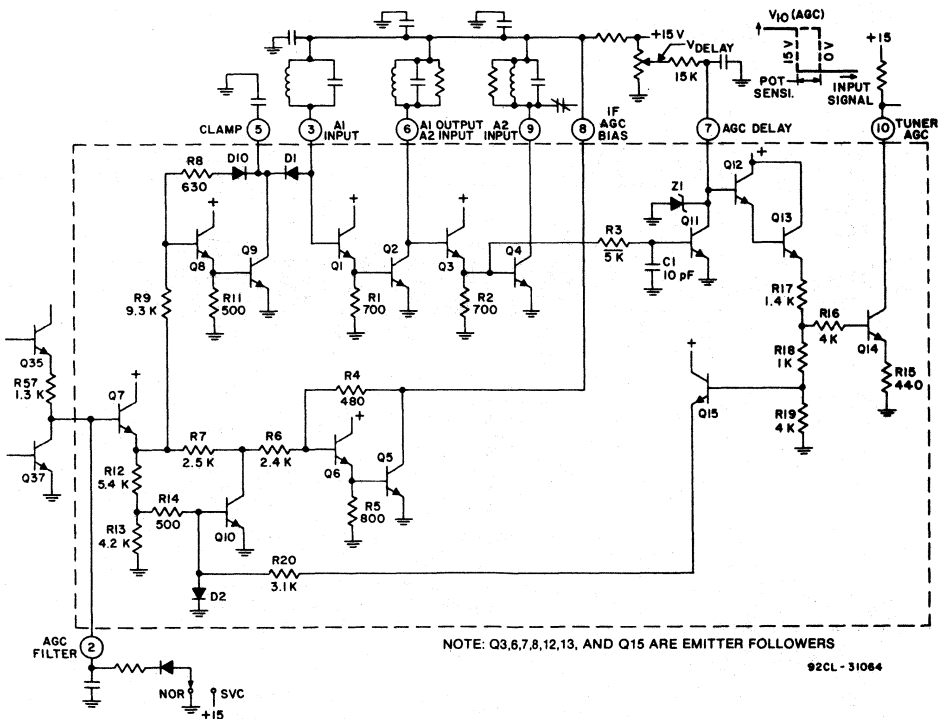


Fig. 4 — IF amplifier and AGC output system of CA3153E (Q1—Q15).

Linear Integrated Circuits

CA3153E

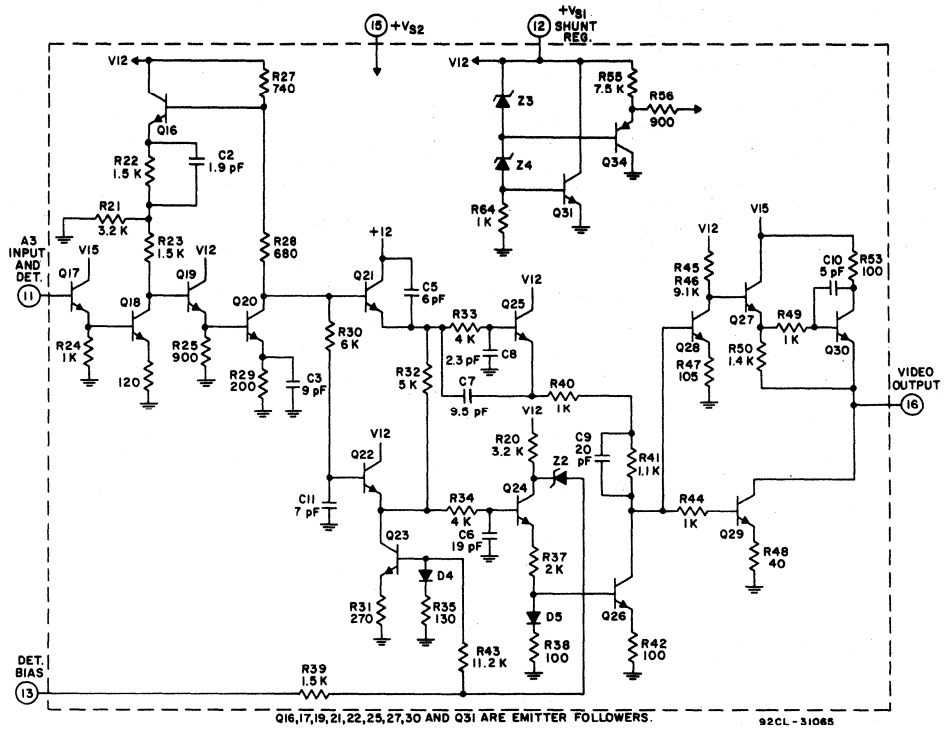
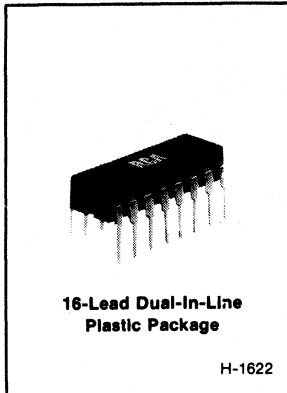


Fig. 5 — Third IF-amplifier stage, detector, and video-amplifier systems of CA3153E (Q16—Q31).



Television Video IF Amplifier, Sync Separator, and AGC Processor

Features:

- High-gain wide-band if amplifiers
- Sample-and-hold keyed agc
- Composite sync separator with noise immunity
- Fast agc using PIN diodes
- Gain reduction with excellent stability
- Internal varactor pole shift at max. gain

The RCA-CA3191E[‡] is a monolithic silicon integrated circuit designed to perform if amplification, forward and/or reverse tuner agc, and composite sync-separation functions in color or monochrome TV receivers.

PIN diodes are used in the if amplifiers for gain control, resulting in increased dynamic range and better signal-to-noise ratio. The CA3191 also includes a varactor in the first if amplifier to improve receiver performance at weak signal conditions and a high-performance sync separator with integral noise inverter protection. In addition to the above new high performance features, the agc performance has been improved through the use of a better sample-and-hold keyed system in comparison to other widely used amplifier-detector video if IC types with integral agc systems.

- Delayed forward and reverse tuner agc
- Low noise - > 55-dB S/N
- 84-dB gain typical when used with CA3192
- +12-V supply

The CA3191E is designed to interface with the RCA-CA3192E* linear video detector, automatic fine tuning (aft), and intercarrier mixer/amplifier.

The CA3191E is supplied in the 16-lead dual-in-line plastic package (E suffix).

[‡]Formerly Dev. Type No. TA10273.

*Refer to the RCA technical data bulletin on the CA3192E.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE:

Between Terms. 11 and 3, 13	14 V
Between 24K connected to Term. 6 and 3, 13	25 V

DC SUPPLY CURRENT:

At Terms. 1 + 2 + 11 + 14 at Max. Gain	60 mA
At Term. 6 (Open Collector)	2 mA

DEVICE DISSIPATION:

Up to T _A =+55°C	750 mW
Above T _A =+55°C	Derate linearly at 7.9 mW/°C

AMBIENT TEMPERATURE RANGE:

Operating	-40 to +85°C
Storage	-65 to +150°C

LEAD TEMPERATURE (During Soldering):

At distance 1/16 ± 1/32 in. (1.59 ± 0.79 mm) from case for 10 s max.	+265°C
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Linear Integrated Circuits

CA3191E

ELECTRICAL CHARACTERISTICS at $T_A=25^\circ\text{C}$, +12-V Supply, Test Circuit - Fig. 7

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
Operating Supply Current	See Note 1 $I_1+I_2+I_{11}+I_{14}$	—	40	60	mA
Supply Current	See Note 2 $I_1+I_2+I_{11}+I_{14}$	15	20.5	30	mA
Initial Alignment	See Note 3 Fixture Tune Volt.	0	8	15	V
Bandwidth 45.75-MHz Response	See Note 4	55	70	85	%
Skew (Pole Shift)	See Note 5	35	60	85	%
Maximum Gain	See Note 6	—	80	—	dB
AGC Gain Reduction	See Note 16	—	80	—	dB
Sensitivity	See Note 6	1.5	3	—	ΔV
AGC Delay 1	See Notes 7, 9	0	0.75	1	mA
AGC Delay 2	See Notes 8, 9	0	100	150	μA
Noise	See Note 10	—	9	11	mV(rms)
Picture/Noise	See Note 11	55	57	—	dB
Sync Output	1	4.5	5	6	V_{p-p}
	2	4.5	5	6	
IF AGC	A@ 50 mV	See Note 13	—	6 V_{p-p}	Ref.
	B@ 5 mV		95	—	110
	C@100 mV		90	—	105
Bar (100 IRE) To Sync	See Note 14	2	2.5	3	Ratio
Sync Tip	See Note 15	1.4	1.8	2.2	V
Input Impedance	See Note 1	—	1K	—	Ω

Notes:

- No signal, agc bias = ground (maximum gain).
- No signal, agc bias = +10 V (minimum gain).
- Adjust sweep generator for 50 mV (rms) across an external 50-ohm termination and sweep width of 10 MHz centered at 44 MHz. Apply sweep signal (without 50-ohm termination) to test-fixture input. Apply positive voltage (0 V to 10 V) to agc bias input on fixture and adjust for a peak response (44 MHz) of 3 V above ground while adjusting fixture tune voltage so that the response at 42.17 MHz and 45.75 MHz are equal. This corresponds to a 5 to 8-V peak-to-peak response curve on an oscilloscope. Measure the fixture bandwidth tune supply voltage.
- Retain tune voltage and agc bias voltage from previous test. Measure response at 45.75 MHz with respect to peak response (44 MHz).
- Retain tune voltage. Reduce amplitude of sweep signal 34 dB [1 mV (rms) across 50 ohms]. Adjust agc bias voltage so that the response at 45.75 MHz is 3 V above ground. Measure response at 42.17 MHz with respect to 45.75 MHz.
- Retain tune voltage. Remove sweep signal. Apply +10 V to agc bias input. Measure video output, V_{OH} . (The voltage will depend on the individual unit of RCA-CA3192E used in the test circuit and will be between 8 and 11 volts.) Remove +10 volts at agc bias input, and ground the agc bias input. Apply a 200- μV signal at 45.75 MHz (as measured across an external 50-ohm termination), and measure the change in the video output voltage with respect to V_{OH} . Note that the actual sensitivity in a TV receiver can be higher because the test fixture includes a 5.2-dB attenuator.
- Retain tune voltage. With agc bias open and video input switch closed, apply a 15-mV (rms) signal (as measured across an external 50-ohm termination) at 45.75 MHz. As the agc delay current is varied from 0 to 1 mA, the reverse tuner output voltage should go from high to low, and forward tuner output from low to high.
- Same as note 7, except increase input signal to 60 mV (rms). As the delay current is varied from 0 to 150 μA , the reverse tuner output voltage should go from high to low and forward tuner output from low to high.
- The reverse tuner agc output is an open collector. A 12 K Ω resistor may be connected to a +12-V supply or a 24 K Ω resistor to a +24-V supply. The output high voltage will be within 1 volt of the supply voltage.
- Apply a 45.75-MHz, 50-mV (rms) signal (as measured across an external 50-ohm termination) to the fixture input. Apply a positive dc voltage to the agc bias input and close the video input switch. Adjust the agc bias for a 2-V reading at the video output. Measure the ac rms noise.

CA3191E

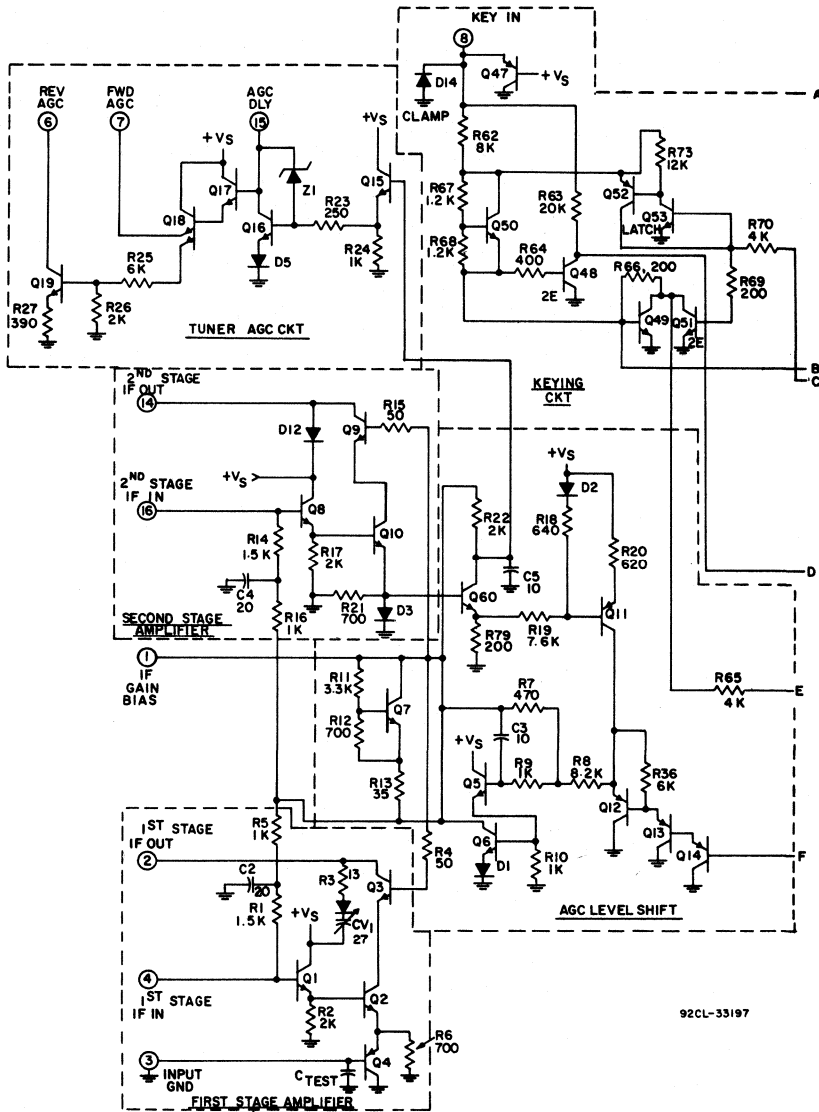
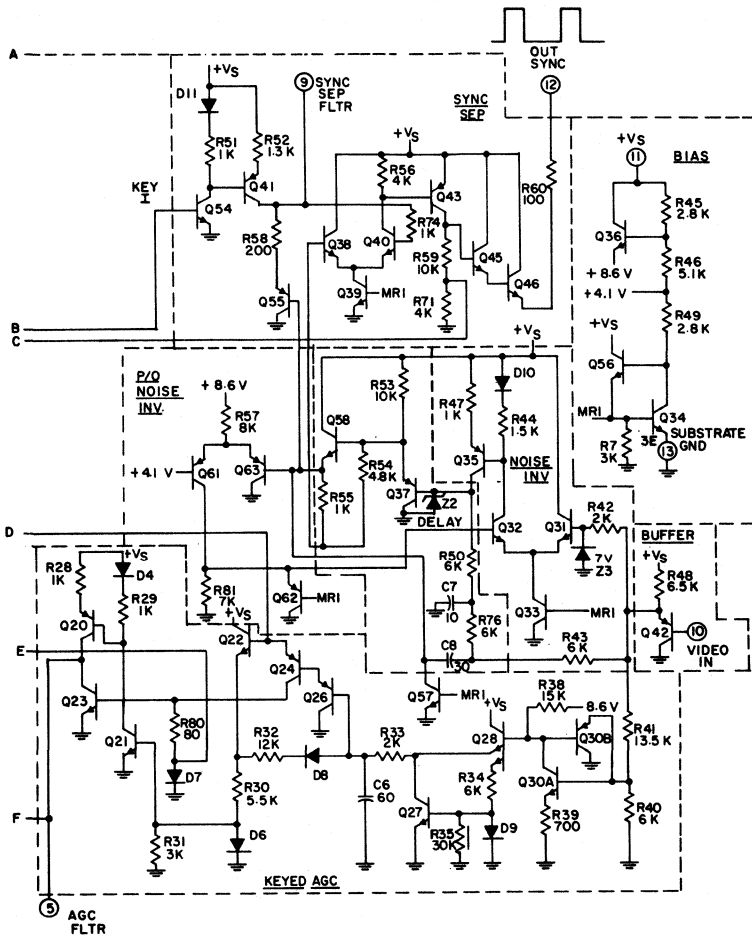


Fig. 2 - Schematic diagram of CA3191E. (Cont'd on next page.)

IF Amplifiers

Fig. 3 shows the schematic of the if amplifier section of the CA3191E. Improved performance is obtained by the use of PIN diodes to control the gain, and an internal varactor to control the tuning of the amplifier at low input signal conditions. The input terminal, terminal 4, is connected to the emitter-follower Q1 whose output is connected to the base of amplifier Q2. The emitter of Q2 is connected to a parallel combination of R6 (700 ohms) and the "anode" of PIN diode Q4. The PIN diode acts as a current-controlled variable resistor which has been designed to minimize its self-capacitance.

At low signal levels the agc voltage applied to terminal 4, through R5 and R1, is high. This high voltage forces Q2 to a high-gain, high-dc-current condition. The high current flows through the anode of PIN diode Q4 to ground, with the result that the PIN diode resistance is low and the gain of the amplifier stage Q1, Q2, and Q3 is high. As the signal level is increased, the agc voltage at terminal 4 is reduced, the operating current of Q2 is decreased, the PIN diode impedance increases, and the amplifier gain is reduced. The degeneration at the emitter of Q2 by the impedance of the PIN diode allows a higher signal level to exist at terminal 4 before overload



92CL-33197

Fig. 2 - Schematic diagram of CA3191E. (Cont'd from previous page.)

conditions. The emitter resistance of Q2 and the PIN diode resistance are about 4.5 ohms each at maximum current (and gain).

The impedance of the PIN diode rises faster than the Q2 emitter resistance as the current is reduced because of the current shunted through R6. At minimum current (and gain), the Q2 emitter resistance is about 40 ohms and the PIN diode resistance is approximately 130 ohms. The linearity and signal-to-noise performance is thus improved in comparison to an amplifier system in which the input signal must be attenuated to prevent overload conditions. The high signal-handling

capability of the amplifier is enhanced by the characteristic of the PIN diodes, which can operate with a signal level about three times as high as the base-emitter signal level of Q2 before distortion commences. The shunt resistor R6 is chosen in conjunction with the PIN diode, Q4, to force most of the input signal, at high levels, to be across the PIN diode and only about one fourth to one ninth across the Q2 emitter-base junction.

The collector of amplifier Q2 is connected to the emitter of the cascode amplifier Q3. The output of amplifier Q3 is connected to terminal 2, and to the series connection of

CA3191E

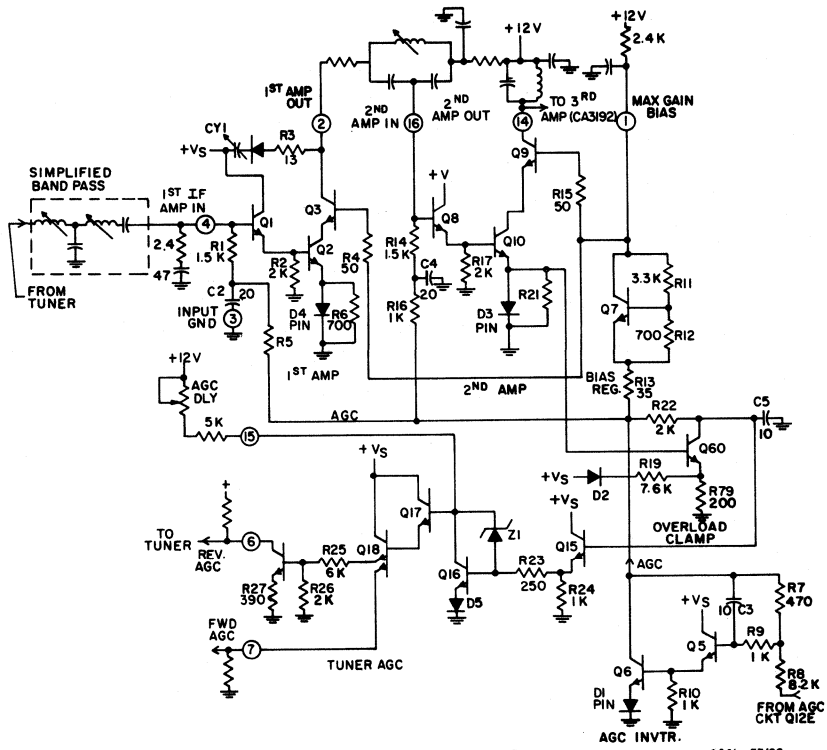


Fig. 3 - IF amplifier and tuner agc circuit.

R3 and voltage-variable capacitance CV1 to the +V supply. The capacitance is reduced at low signal levels; as a result, the response of the amplifier is peaked in the region of the picture carrier. An external tuned circuit is connected through a small resistor from terminal 2 to the +V supply. The output of the tuned circuit is ac coupled to the input of the second stage of the IF amplifier at terminal 16. This stage is similar in operation to the first stage just described, except that no varactor is used at the output. The second stage amplifier consists of Q8, Q10, Q9, PIN diode D3, and associated components. A tuned circuit is also connected between the output of the second amplifier, terminal 14, and the +V supply, and the amplified signal is ac coupled to the input of the CA3192E amplifier/detector.

The agc voltage at terminal 5 (refer to Fig. 4(b)) is buffered by emitter followers Q14, Q13, and Q12 and connected to the feedback inverting amplifier Q5 and Q6 through resistor R8. The inverting amplifier also uses a PIN diode in the emitter of Q6 to provide temperature compensation. Transistor Q7 acts as a low-voltage zener (≈ 4.2 V or $6 V_{BE}$) to translate the if agc potential at the collector of Q6 (and the bases of Q1 and Q8) to the base of the grounded-base cascode amplifiers Q3 and Q9.

At very low signal levels, the agc voltage at

terminal 5 is low, and the dc voltage level at Q6 collector is high, about $3 V_{BE}$ (≈ 2.1 V) above ground. For these conditions, the if amplifiers operate at maximum current and gain. The current may be adjusted by selecting the value of an external resistor connected between terminal 1 and +V supply. The voltage at the bases of Q3 and Q9 are at approximately $9 V_{BE}$ (≈ 6.3 V) above ground. As the signal level increases, the agc voltage increases at terminal 5, and the inverted output at the collector of Q6 decreases. This action reduces the if amplifier currents, and the PIN diode impedance rises, reducing if amplifier gain as previously described.

Near the level of maximum reduction in if gain, the tuner agc may be set to start gain reduction for stronger signal levels. For best S/N and overload performance, this agc action should be set to start when the input and output signal levels at terminals 4 and 16 are approximately 40 mV (gain ≈ 1).

The tuner agc delay point may be adjusted by changing the injection current into terminal 15 of the CA3191E. Tuner delay is decreased for a high injection current into terminal 15 because the base current at Q16 is insufficient to maintain Q16 collector saturated. The tuner delay is increased for low injection currents into terminal 15 because the base current is sufficient to keep Q16 saturated at low collector currents.

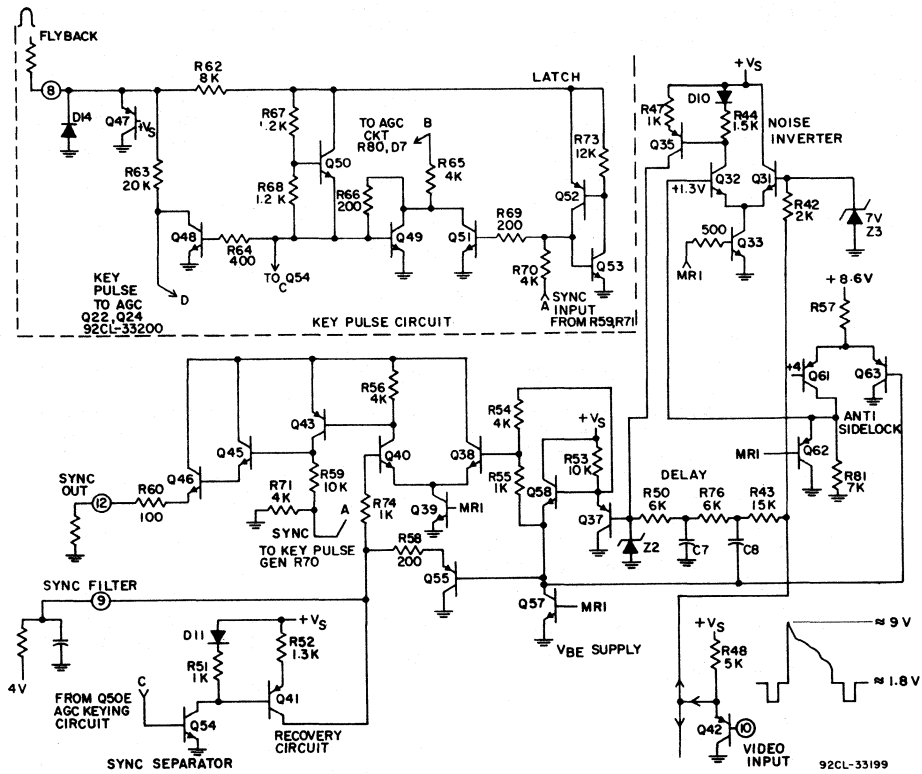


Fig. 4(a) - Sync separator and key pulse circuit.

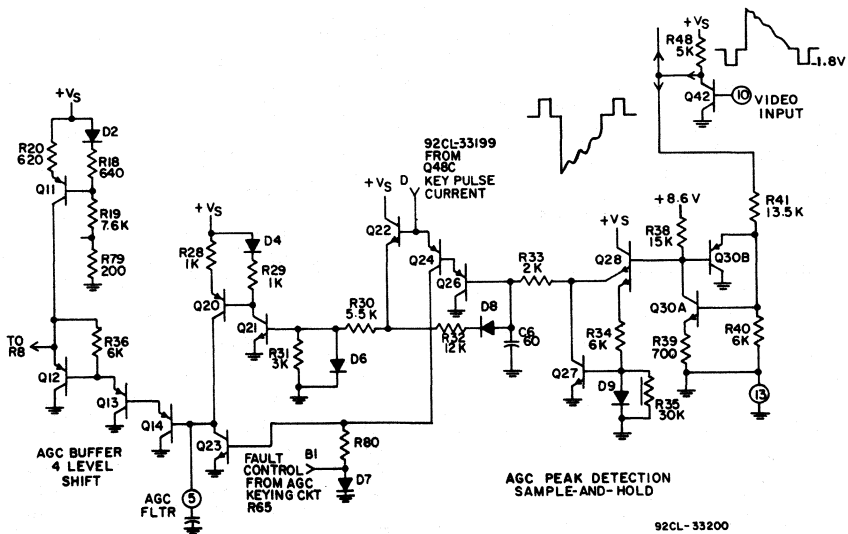


Fig. 4(b) - Keyed agc circuit.

CA3191E

Sync Separator

Fig. 4(a) shows a simplified schematic of the noise-protected sync-separator circuit of the CA3191E.

The video input (negative-going sync) at terminal 10 is buffered by emitter follower Q42, which is emitter-coupled to the noise inverter and the sync separator. The input (sync tips ≈ 1.8 V) to the sync separator is through an active RC delay circuit consisting of resistors R43, R76, C7, C8, Q37, and Q58.

The output of the noise inverter at Q35 is combined with the delayed video signal at the base of Q37, resulting in a noise-cancelled video signal. (The noise inverter, Q31, Q32, Q35 and associated components, inverts negative-going noise pulses when they become more negative than the reference bias at the base of Q32.) Because the inversion occurs before the delayed signal appears at the junction of the delay circuit and the base of Q37, the leading edge of the noise pulse is cancelled before reaching sync tip amplitude. The noise-cancelled signal is amplified by Q37 and Q58. Feedback from Q58 is applied to filter capacitor C8 in order to improve the rise time of the sync pulses. The output signal at Q58 is applied to the base of Q55, which acts as a peak detector, and also to the base of Q38 through resistor R55. A voltage divider consisting of R54 and R55 assures that the dc level of the signal at the base of Q40 is higher than that of the base of Q38. The emitter of Q55 is one V_{BE} above the emitter of Q58. During the time that sync (or equalizing) pulses are present, the external capacitor is discharged toward the potential at the emitter of Q55. The negative-going sync pulse at the base of Q38 quickly falls below the slicing level set by the peak detector. The time constant (and slicing level) of the peak detector is user selected by the components connected to the sync filter at terminal 9. A resistor is also normally connected from terminal 9 to a positive voltage to supply the bias current required for Q55.

Thermal noise detection may be minimized by connecting an inductor and damping resistor in series with the peak-detector capacitor connected to terminal 9. The inductor reduces the bandwidth of the peak detector.

The output of the peak detector is applied to the base of Q40 through resistor R74. Transistors Q38, Q39, and Q40 form a differential amplifier with Q39 acting as a constant-current sink for the emitters of Q38 and Q39. As noted previously, the delayed noise-inverted video signal is applied to the base of Q38 (normally on) and the output of the peak detector is connected to the base of Q40 (normally off).

The differential-amplifier transistors Q38 and Q40 act as a threshold detector, and the output at the collector of Q40 consists of a "slice" of the sync signal. The reference voltage at the base of Q40 varies according to the input sync amplitude, thus tracking the sync input at the base of Q38 to maintain optimum sync separation. This action prevents "sidelock" which could result if the amplitude of the sync signal became high enough to cross the noise-threshold bias. The noise inverter would then treat the sync as a noise pulse and invert it.

The output of the differential amplifier at the collector of Q40 is connected to a p-n-p inverter/amplifier, Q6, which, in turn, is connected to an agc keying circuit and to the base of the output cascade emitter followers Q45 and Q46 and then to terminal 12 of the CA3191E. The output at terminal 12 consists of stripped positive-going composite vertical and horizontal sync pulses. An external load resistor is connected between terminal 12 and ground.

An output from the AGC keying circuit is connected to the base of Q54. Transistors Q54 and Q41, together with resistors R51, R52, and diode D11, form a recovery circuit for the sync separator.

During a sudden signal fade, or during channel switching from a strong channel to a weak channel, the tips of the sync pulses may momentarily rise above the slice level. Until the agc circuit returns the video signal to normal levels, the sync will be missing. The recovery circuit reduces this time interval by responding to the loss of sync condition from the agc keying circuit, when the sync pulses are not coincident with keying pulses. During the loss of sync condition, the output of the agc keying circuit couples pulses from the keying pulse source to the base of Q54. Transistors Q54 and Q41 are consequently turned on and the current from Q41 rapidly charges the external filter capacitor at terminal 9. The sync slice level is then raised so that peak detection can commence, and normal sync separation is quickly restored. This circuit, therefore, allows a higher capacitance value for the filter, which minimizes ripple on the slicing level without the penalty of a long recovery time.

At low level signal conditions, thermal noise from the antenna, tuner, and if amplifiers tend to degrade separation. To improve the performance of the sync separator under such conditions, transistors Q55 and Q43 are constructed to have narrow bandwidth which attenuates high-frequency noise in the peak detector. The noise bandwidth can also be reduced by using an RL coupling network between terminal 9 and the capacitor.

Noise Inverter and Anti-Side-Lock Circuits

In normal operation the video signal (negative-going sync) applied to terminal 10 is coupled through emitter follower Q42 and R42 to the noise detector consisting of the comparator circuit Q31, Q32, and Q33. At terminal 10, the tip of the sync pulse is nominally at 1.8 volts, while the black level is nominally 3.8 volts. The voltage-translated sync tip level at the base of Q31 is 2.5 volts and is compared to a nominal 1.3-volt reference at the base of Q32. In the event that negative-going noise pulses fall below the reference voltage, transistors Q32 and Q35 conduct and apply a positive-going inverted noise pulse at the base of Q37, which is added to the delayed signal from the active filter formed by R43, R76, R50, C7, and C8.

Because the video signal containing sync and noise has been delayed by the filter, the leading edge of the noise pulse is cancelled before the noise pulse reaches the sync tip level. The inverted noise pulse also charges capacitors C7 and C8 in the filter, thus stretching the inverted pulse to totally encompass and invert the original noise pulse.

The dc coupling used in the noise-threshold detector could result in an improper operating mode known as "sidelock" under certain operating conditions, e.g., receiver turns on or channel changes when the amplitude of the video signal is momentarily high, and the sync tips could fall below the noise inverter threshold. The noise inverter would treat the sync pulses as noise and remove them by the action of the inverter. The front and back porches of the horizontal line would appear to be two sync pulses, and the horizontal oscillator in the receiver would lock up to one of them. This mode is prevented by the anti-sidelock circuit consisting of another comparator (Q61, Q63, and associated components). Under normal signal-level conditions, the front and back porches and the black level portion of the video signal are above 4.5 volts at the emitter of Q58. The reference voltage at the base of Q61 is 4.1 volts so that Q61 supplies current to Q62 and R81. The base of Q62 is reference-biased to $1 V_{BE}$ and the emitter of Q62 is, therefore, $2 V_{BE}$ above ground (1.3 V) and the noise inverter functions as previously described.

If, during turn-on or channel-changing, the amplitude of the video signal momentarily increases and the sync porches fall below 4.1 volts at the base of Q63, then Q61 turns off, the voltage at the base of Q32 collapses to zero volts, and the noise inverter is disabled until the agc circuit restores the video to normal levels.

AGC Keying Circuit

The agc keying circuit in the CA3191E utilizes the coincidence existing between the video sync pulse and the horizontal flyback (retrace) pulse to provide improved noise immunity, higher response speed, and reduction of "set up" at vertical sync time. An internally processed keying signal begins upon coincidence of the sync pulse and ends upon termination of the retrace pulse, thus maintaining the key pulse essentially constant and independent of the length of the sync pulse which can vary from $2.5\mu\text{s}$ for the equalizing pulses to $29\mu\text{s}$ for the vertical serration pulses. The circuit also provides an out-of-lock signal for the agc circuit and the sync-separator recovery circuit.

Fig. 4(b) shows a simplified schematic of the agc circuit. In normal operation the key pulse (width $\approx 12\mu\text{s}$) applied to terminal 8 is in coincidence with the sync pulse, derived from Q43, R59, R71, and R70 in the sync separator and applied to the base of Q53. Transistors Q52 and Q53 form a latch circuit that is turned on by the leading edge of sync and remains in its conducting state until the keying pulse decays to zero volts. The keying pulse, clamped by Q47 to $V_S + 1 V_{BE}$, is coupled to the latch circuit by R62 and also to the collector of Q50. The sync pulse (constant width by the action of the latch circuit), is applied to the base of Q51, turning on this transistor and preventing outputs to the agc and sync recovery circuits. The base of Q48 is held at cutoff by the low potential at Q51 through resistors R66 and R64. The keying pulse for the agc circuit, therefore, flows through R63, and the agc circuit is then keyed normally.

If the key pulse and sync pulse are not coincident (out of sync), the normal agc pulse is disabled and an out-of-lock signal is coupled to the agc and sync recovery circuits as follows: The latch formed by transistors Q52 and Q53 does not operate unless current is supplied to the emitter of Q52 at the same time that a sync pulse is supplied to the base of Q53. When a horizontal key pulse is applied to terminal 8 without a coincident sync pulse, transistors Q50 and Q48 are turned on by the key pulse through R62, R67, R68, and R64. Transistor Q48 then prevents the flow of the key pulse current to the agc circuit. The keying pulse, attenuated by Q49 (also turned on), is applied to the agc recovery circuit where it turns on Q23 and slightly discharges the agc filter capacitor at terminal 5 and increases the gain of the if and rf stages. The key pulse, as previously explained, is coupled from the emitter of Q50 to the sync recovery circuit.

In the event of receiver turn-on or channel

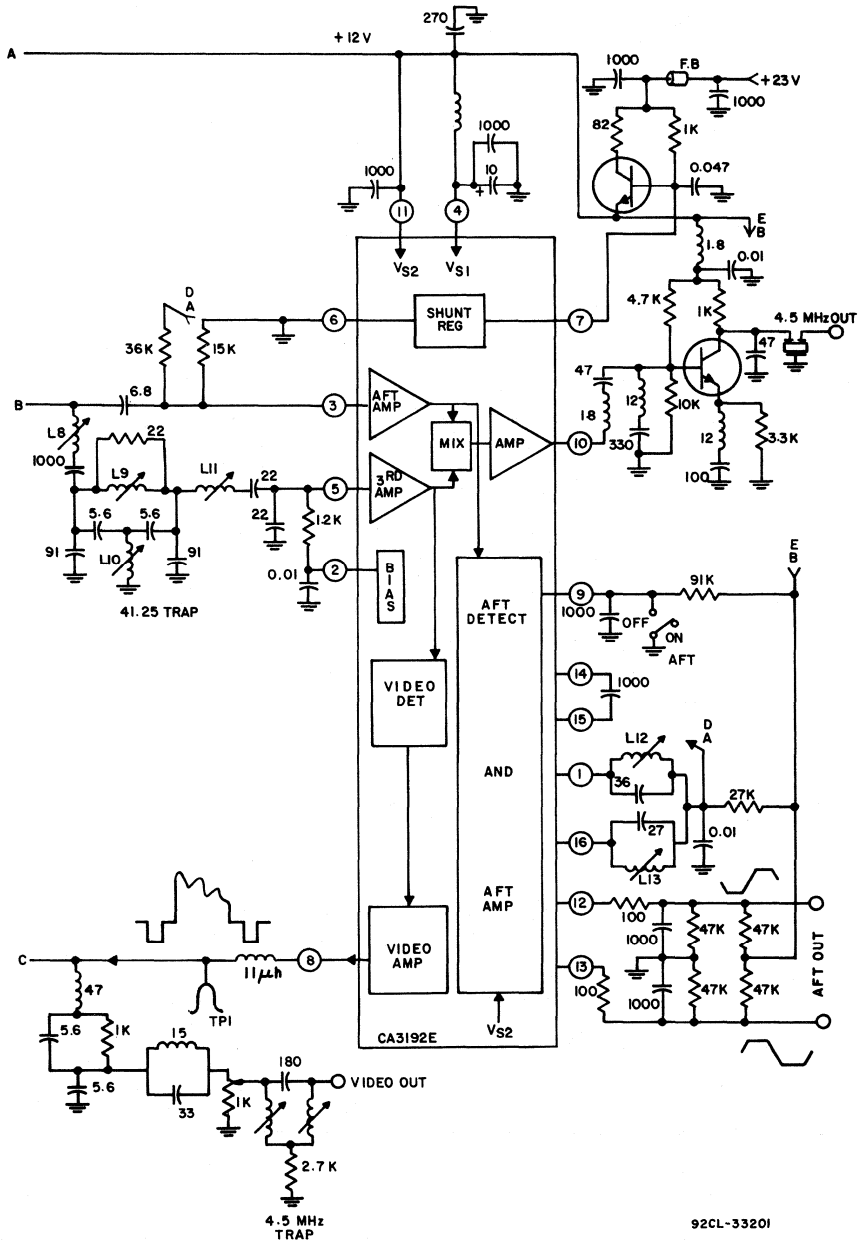


Fig. 5 - Application circuit for CA3191E and CA3192E. (Cont'd from previous page.)

The input of the agc circuit is a switch consisting of Q30A and Q30B. The signal is inverted by Q30A and applied to multiple emitter follower Q28.

At conditions of zero or very weak signals, Q30A tends to saturate. This saturation of Q30A is prevented by the conduction of Q30B. The load resistance, R38, for the inverter is connected to an 8.5-volt supply to correctly bias C6. The peak sync signal charges the storage capacitor C6 through resistor R33.

Under normal operation a key pulse is applied simultaneously to the base of Q22 which turns on to reverse bias D8 so that C6 will not discharge through R32, R30, and R31. The voltage stored on C6 should be dependent only on the amplitude of the sync component of the video signal and not be influenced by the widths of the sync pulses (2.5 µs to 29 µs). The impedance of an emitter follower increases at low emitter currents and the charge on C6 would not follow short equalizing pulses. This action

CA3191E

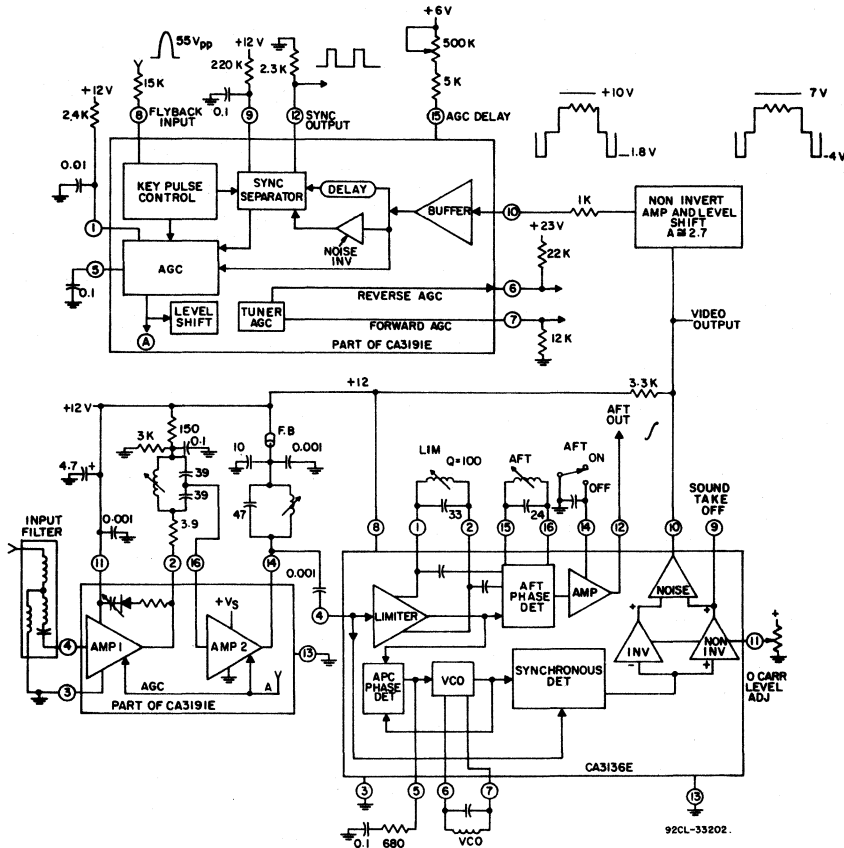


Fig. 6 - Application block diagram of CA3191E and CA3136E synchronous detector.

is corrected by the output from the second emitter on Q28, resistors R34, R35, D9, and Q27 which acts to keep the emitter-follower impedance low as the capacitor C6 is reaching full charge. At high signal levels, current from the second emitter is forced into R35 and D9 through R34. This current is fractionally mirrored into Q27, which acts to lower the output impedance of the first emitter of Q28 by providing a current path through the collector and emitter of Q27. At the end of the sync time, Q27 and Q28 are turned off because the emitter-base junction is back-biased by the peak sync voltage charge on C6.

When the key pulse is applied to the base of Q22, its emitter current also turns on Q21 through resistor R30. The key pulse is clamped $2 V_{BE}$ higher than the peak voltage stored on C6 so that the current conducted to the base of Q21 by R30 is dependent on the detected sync pulse amplitude. Transistor Q20 is turned on by Q21, and the output current charges the external capacitor at terminal 5. Some or all of the charge current may be diverted by Q23. When the key pulse is applied to the base of Q22, it also supplies the emitter

current required for Q24 emitter. The collector current of Q24 is coupled to the base of Q23 causing it to conduct. The amount of conduction of transistors Q20 and Q23 depends on the sync-tip amplitude stored on C6. For weak signals Q23 sinks most of the current and the agc filter at terminal 5 is discharged toward ground. During increasing high signal levels, Q20 supplies charging current to the terminal 5 filter capacitor. This charging increases the positive voltage on C6 causing reverse bias to Q26 and Q24 which, in turn, reduces base current to Q23. Under equilibrium conditions, Q20 and Q23 collector currents are identical and the voltage at terminal 5 does not change. The net increase of charge to the filter capacitor at terminal 5 increases the terminal 5 agc voltage as the signal level increases, and the if and rf gains are decreased to maintain a uniform signal level at terminal 10.

When the receiver is not in synchronism, the key pulse is removed from the base of Q22 by the latch circuit. Under these conditions, C6 is discharged between successive TV lines by D8, R32, R30 and R31. Therefore any noise on the video

signal does not build up on C6 to cause agc noise set up. Both Q20 and Q23 are turned on only during the retrace interval and remain at cutoff during the active trace time period. As a consequence, the value of the agc filter capacitor at terminal 5 can be a relatively low value ($\approx 0.1 \mu\text{F}$).

When the keying pulse is not present at the base of Q22, a small positive pulse from the latch circuit is applied to the junction of D7 and R80 which, in turn, lets Q23 conduct a

small current to discharge the agc filter at terminal 5 which increases the if and rf gain to allow the sync separator and latching circuit to quickly acquire synchronization.

When very strong signals occur (channel switching, etc.), keying pulses are continuously applied to the base of Q22 and the input to D7 is grounded reducing the gain of the if and rf stages to assure quick return to normal operation.

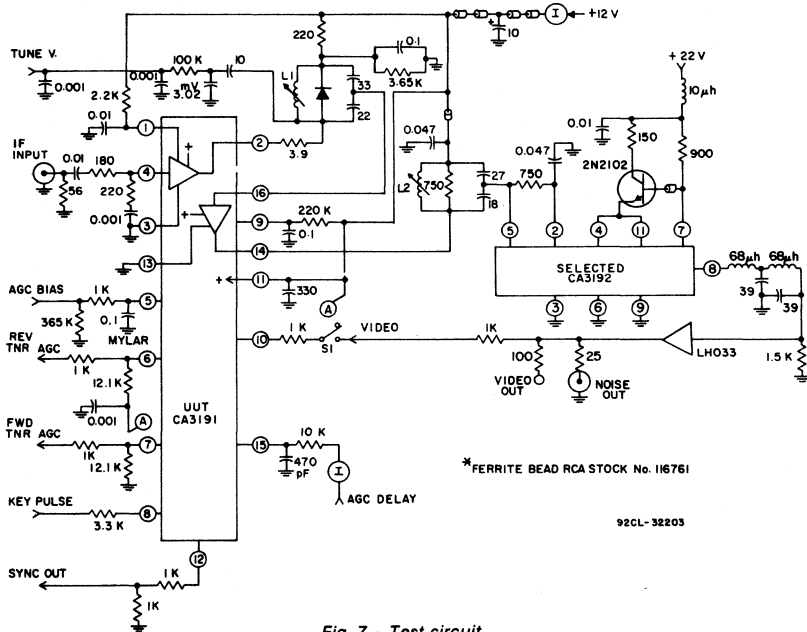
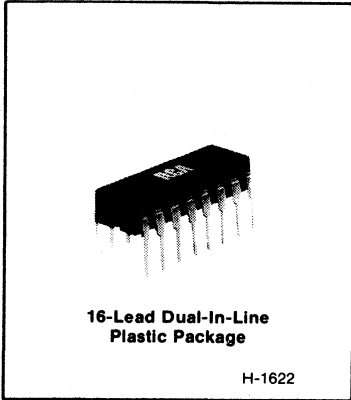


Fig. 7 - Test circuit.

CA3192E



Television Video IF Amplifier System

Includes 3rd Stage IF Amplifier, Video Detector, Video Amplifier, Inter-carrier Mixer/Amplifier (Sound), AFT, and Shunt Regulator

Features:

- Gain 41.5 dB \pm 3 dB if input to video output
- Picture-to-noise - 55 dB min.
- Linearity - \pm 5% (5 steps black to white)
- Zero carrier output - 10 V typical
- 4.5 MHz intercarrier output - 30 mV_(RMS) typical
- AFT slope - 72 V/MHz min.
- Shunt regulator voltage - 13 V typical
- Differential gain - 7.5% typical
- Differential phase - 7.5° typical

The RCA-CA3192E‡ is a monolithic silicon integrated circuit designed to perform the third stage IF amplification, video detection, video amplification, sound intercarrier mixing and amplification, and aft functions in color or monochrome TV receivers. The circuit also includes a shunt voltage regulator for use with the if system.

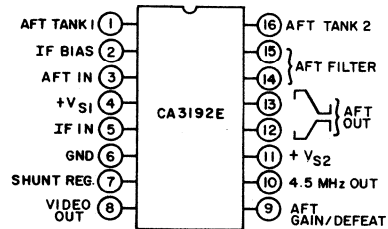
The CA3192E is designed to interface with the RCA-CA3191E* if amplifier, sync separator, and agc processor.

The CA3192E is supplied in the 16-lead dual-in-line plastic package (E suffix).

‡Formerly Dev. Type No. TA10280B.

*The CA3191E is described in RCA data bulletin File No. 1268.

Terminal Assignment



92CS-33876

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE:

Between Terms. 4 and 6	14 V
Between Terms. 11 and 6	24 V
Between 1 K connected to Term. 7 and 6	25 V

DC SUPPLY CURRENT:

At Term. 7	12 mA
At Term. 4	40 mA
At Term. 11	6 mA

DEVICE DISSIPATION:

Up to T _A = +55° C	750 mW
Above T _A = +55° C	Derate linearly at 7.9 mW/° C

AMBIENT TEMPERATURE RANGE:

Operating	-40 to +85° C
Storage	-65 to +150° C

LEAD TEMPERATURE (During Soldering):

At distance 1/16 \pm 1/32 in. (1.59 \pm 0.79 mm) from case for 10 s max.	+265° C
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ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$ and referenced to Test Circuit (Fig. 3)

Test	Characteristic	Measure	Notes or Test Conditions	Limits			Units
				Min.	Typ.	Max.	
1	Shunt Regulator Voltage	TPW (V7)		6 (12)	—	7.05 (14.1)	V
2	Supply Current	I4	V4 = 12 V	13.5	—	38.5	mA
3	Supply Current	I11	V11 = 12 V	1.5	—	5.1	mA
4	Video Output at Zero Carrier	TP14 (V8)	No Signal	4.05 (8.1)	—	5.5 (11)	V
5	Change at Video Output $\Delta V8$		J1 Input Signal 60 mV _{RMS} 45.75 MHz Response at 3.58	2.5 (5)	—	5 (10)	TP14 V8 ΔV
6	Video Response	TP16	MHz with respect to Response at 1 MHz N1	-1.5	—	1.5	dB
7	Noise	J4	45.75 MHz CW at J1. N2	—	—	10	mV _{RMS}
8	Sync Tip Voltage	TP16	Normally Determined By AGC Action of CA3191E	1.4	—	2.2	V
9	Linearity	TP16	$\frac{B}{F}$ N3	15	20	25	%
10			$\frac{C}{F}$ N3	35	40	45	%
11			$\frac{D}{F}$ N3	55	60	65	%
12			$\frac{E}{F}$ N3	75	80	85	%
13			$\frac{G}{F}$ N3	106	120	134	%
14			$\frac{A}{F}$ N3	30	40	50	%
15			Inter-carrier Output	J3	J1 45.75 MHz, 40 mV _{RMS} J2 41.25 MHz, 10 mV _{RMS}	10	30
16	AFT Outputs	45.75 MHz TPJ	J2 f ₀ , 20 mV _{RMS} N4 N5	5.2	6	6.8	V
17		45.75 MHz TPL	J2 f ₀ , 20 mV _{RMS} N4 N5	-0.6	—	0.6	ΔV WRT* T16
18		45.25 MHz TPJ	J2 f ₂ , 20 mV _{RMS} N4 N5	0.03	—	0.6	V
19		44.65 MHz TPJ	J2 f ₁ , 20 mV _{RMS} N4 N5	0.1	—	4.3	ΔV WRT T18
20		45.725 MHz TPJ	J2 f ₃ , 20 mV _{RMS} N4 N5	0	—	2.7	ΔV WRT T18
21		46.25 MHz TPJ	J2 f ₅ , 20 mV _{RMS} N4 N5	11.2	—	12	V
22		46.85 MHz TPJ	J2 f ₆ , 20 mV _{RMS} N4 N5	-0.1	—	-4.3	ΔV WRT T21
23		45.775 MHz TPJ	J2 f ₄ , 20 mV _{RMS} N4 N5	0	—	-2.7	ΔV WRT T21

*With respect to

Linear Integrated Circuits

CA3192E

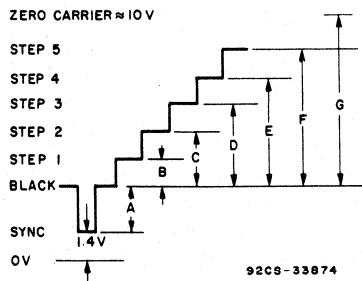
ELECTRICAL CHARACTERISTICS *Continued*

Test	Characteristic	Measure	Notes or Test Conditions	Limits			Units
				Min.	Typ.	Max.	
24	AFT Outputs	45.25 MHz TPL	J2 f ₂ , 20 mV _{RMS} N4 N5	11.2	—	12	V
25		44.65 MHz TPL	J2 f ₁ , 20 mV _{RMS} N4 N5	-0.1	—	-4.3	ΔV WRT* T24
26		45.725 MHz TPL	J2 f ₃ , 20 mV _{RMS} N4 N5	0	—	-2.7	ΔV WRT T24
27		46.25 MHz TPL	J2 f ₅ , 20 mV _{RMS} N4 N5	0.03	—	0.6	V
28		46.85 MHz TPL	J2 f ₆ , 20 mV _{RMS} N4 N5	0.1	—	4.3	ΔV WRT T27
29		45.775 MHz TPL	J2 f ₄ , 20 mV _{RMS} N4 N5	0	—	2.7	ΔV WRT T27
30	AFT Defeat	45.25 MHz TPL	J2 f ₂ , 20 mV _{RMS} N4 N5	5.2	—	6.8	V
31	AFT Defeat	45.25 MHz TPJ	J2 f ₂ , 20 mV _{RMS} N4 N5	5.2	—	6.8	V

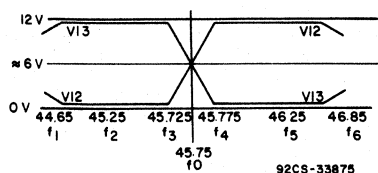
*With respect to

NOTES:

- Frequency Response** — combine two signal sources by means of a 3-port 50-ohm resistive combiner.
 Port 1 — 45.75 MHz CW Signal Source.
 Port 2 — 44.75 MHz or 42.17 MHz CW Signal Source.
 Port 3 — J1 (IF input)
 With signal generator connected to port 2 set at zero output, adjust the amplitude of the 45.75 MHz signal connected to port 1 until the dc voltage at test point 16, TP16, is 4 volts dc. Increase amplitude of 44.75 MHz signal at port 2 until the resultant 1 MHz beat at TP16 is 1 V_{RMS}. This signal represents 0 db.
 Change 44.75 MHz source to 42.17 MHz and measure the amplitude of the resultant 3.58 MHz signal.
 This amplitude is compared to the 1 V_{RMS} 1 MHz signal.
- Noise** — Adjust amplitude of CW signal (45.75 MHz) at J1 until the dc voltage at TP16 is 4 V dc. Measure RMS noise using a video voltmeter with its low capacitance probe connected to J4.
- Linearity** — Apply a 100-IRE, 5-Step 87.5% modulated IF signal to J1 of the test fixture. Adjust the modulated IF signal amplitude until the sync tip voltage is 1.4 volts.



4. AFT Response.



NOTES: (Cont'd.)

5. AFT Tuning — Align "bow tie" curve for best fit to specifications by adjusting varactor voltages at TP6 and TP7. Most units will have adequate bandwidth when tuned for maximum slope at center frequency. Readjust, if necessary, for optimum compromise between slope and bandwidth.

Initial Fixture Alignment — Apply 5.5 volts to TP6 and TP7. Adjust cores L1 and L2 using a correlation unit for best fit curve.

Test Method: First Alignment — Apply 10.2 V to TP6 (Varactor 1). Apply 46.25 MHz at 20 mV_{RMS} to J2 and adjust Varactor 2 (TP7) voltage for a resultant difference of zero volts between test points J and L. Hold TP7 voltage and change frequency to 45.75 MHz and adjust TP6 voltage for difference of zero volts between test points J and L. Hold both varactor voltages for bow tie tests 16 thru 17. If unit fails tests, repeat using second alignment method.

Test Method: Second Alignment — Same as first alignment method except apply 9.7 volts to TP6, and then repeat balance of first alignment steps.

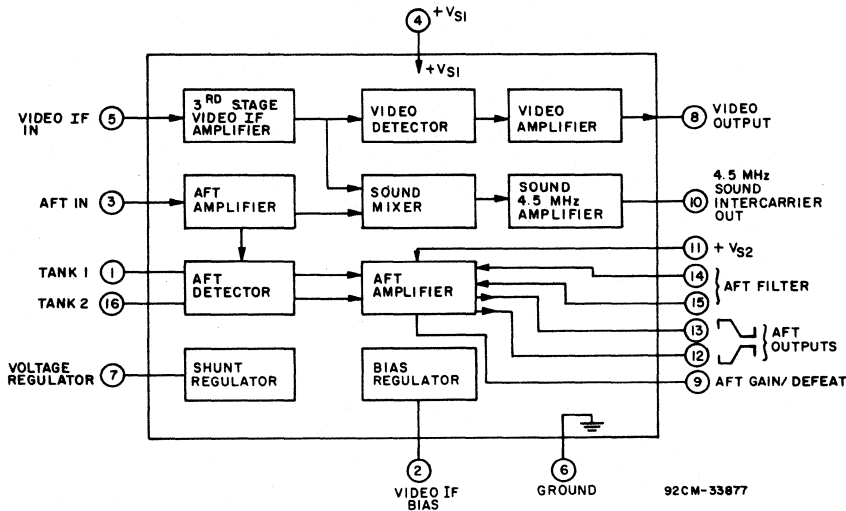


Fig. 1 - Block diagram of CA3192E.

Circuit Description

Figs. 1 and 2 show the block diagram and schematic, respectively, for the CA3192E.

The video if signal, including the sound carrier, is applied to the third stage of the if amplifier at terminal 5. Transistors Q28 through Q32 amplify the signal. The internal RC components form a low-Q bandpass amplifier centered at approximately 44 MHz. Transistor Q36 is biased at the threshold of conduction by a temperature compensated bias circuit consisting of transistors Q37, Q38, Q39 and Q40.

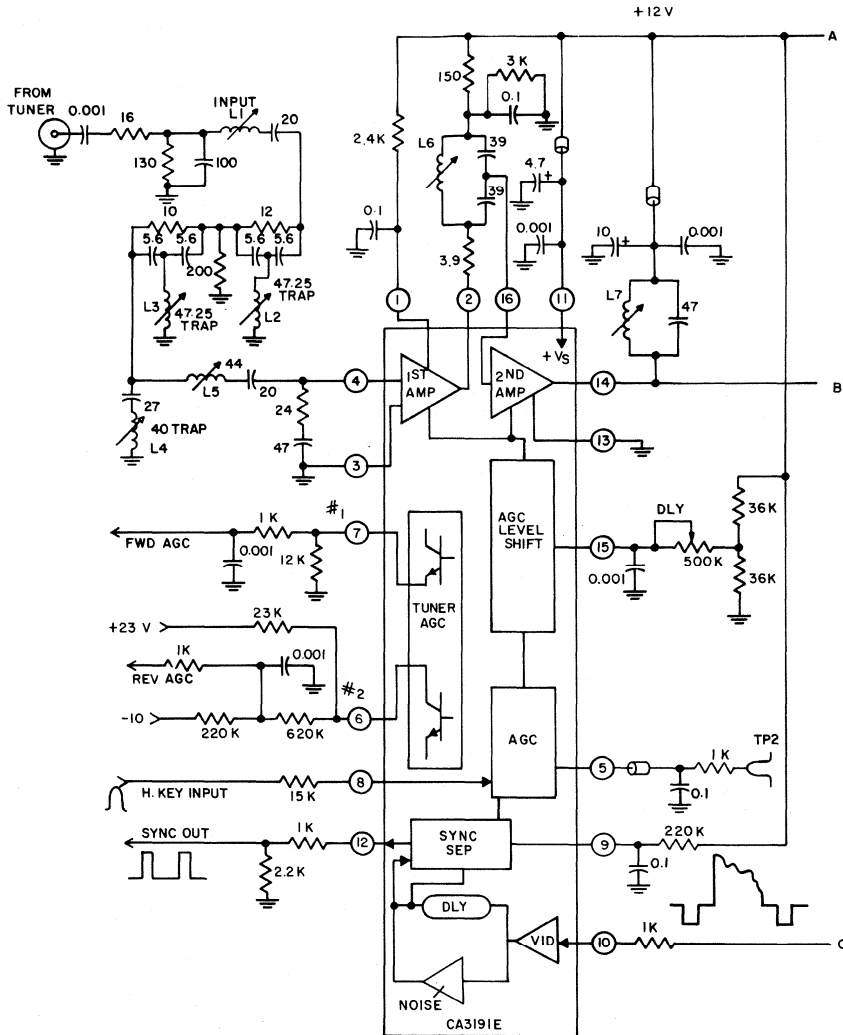
Transistor Q36 performs the video detection function. The if carrier is filtered out by the low-pass circuit components C12, R44, C10, Q35 and C11.

The detected video signal at the emitter of Q35 is connected to the current mirrors consisting of D7, R130, Q42, R58, Q45, and R60. The amplified video signal appears at output terminal 8. Zero signal input at terminal 5 results in an output dc level of approximately 10 volts at terminal 8.

The amplified if signal at the collector of Q32 is also buffered by emitter-follower transistors Q34 and Q33. This if signal is connected to the upper base of the cascode-connected mixer Q4 and Q5 which converts the picture carrier (nominally 45.75 MHz) and the audio carrier (nominally 41.25 MHz) to a 4.5-MHz FM modulated sound carrier. The high-frequency carriers are filtered by the RC components associated with transistors Q1 and Q2. The 4.5-MHz sound carrier output is at terminal 10.

The picture if carrier (45.75 MHz) is applied to emitter-follower Q3 at terminal 3 of the CA3192E. The output of the emitter-follower is connected to the base of the sound mixer Q5, as previously described, and to the AFT system comprised of transistors Q6 through Q27.

The output of transistor Q6 is connected to the grounded-base amplifiers Q7 and Q8. External tuned circuits are connected to the collectors of Q7 and Q8 at terminals 1 and



INDUCTOR	RCA STOCK No.	INDUCTOR	RCA STOCK No.
L1	146195	L7	146199
L2,L3	146196	L8	146200
L4	146197	L9	146201
L5,L11	146198	L10	146202
L6	146203	L12	146204
		L13	143897

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Fig. 4 - Application circuit for CA3191E and CA3192E. (Cont'd on page 7).

The outputs of the envelope detectors are applied to the dc amplifiers Q25 through Q27.

The dc amplifier gain can be controlled by adjusting the bias current fed into terminal 9, and the AFT can be defeated by reducing the input current at terminal 9 to zero. ($V_9 \leq 0.5$ V).

Included in the circuit is a reference shunt regulator connected to terminal 7.

Applications

Fig. 4 shows a typical application of the CA3192E used with a CA3191E television video if amplifier, sync separator, and AGC processor. Note that no mutual coupling is used between the inductors L12 and L13.

Fig. 5 is a partial schematic of an alternate AFT detector circuit using a discriminator transformer.

CA3192E

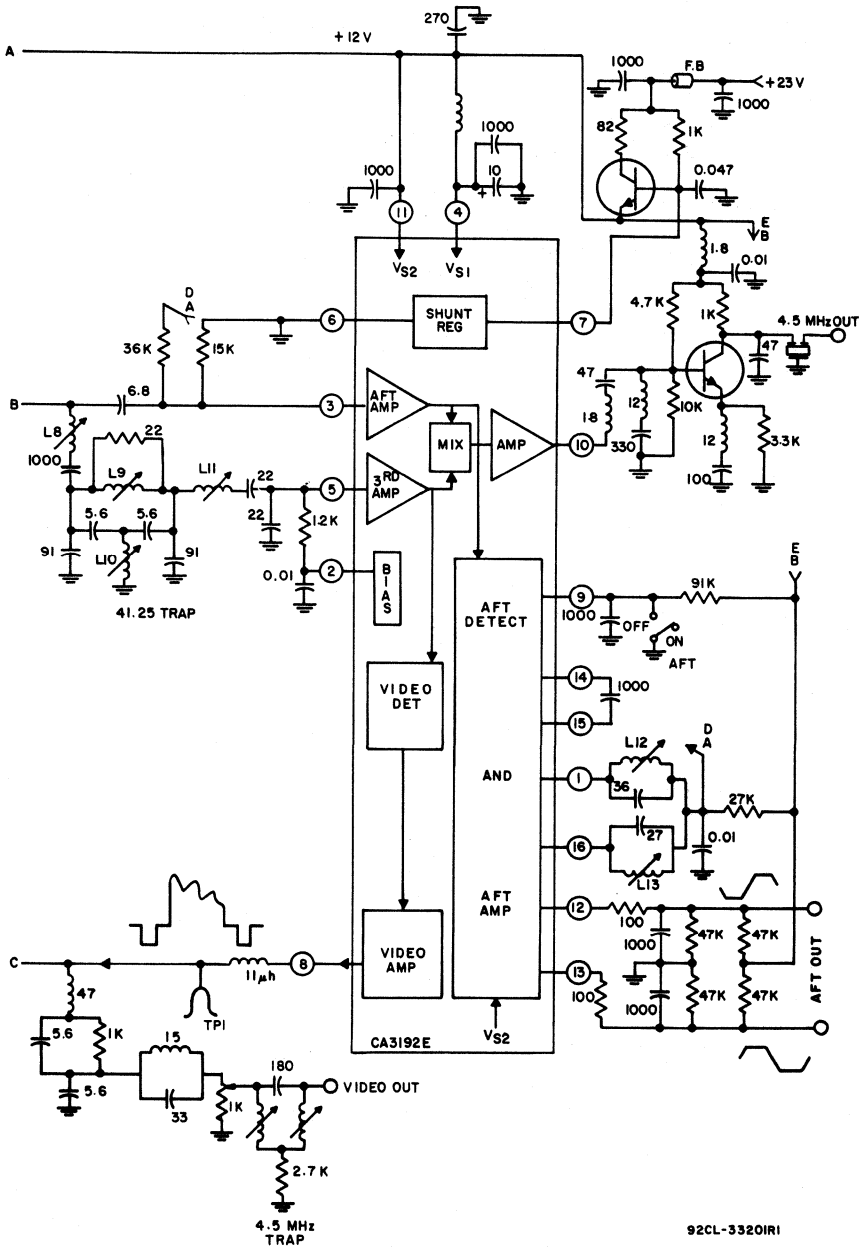


Fig. 4 - Application circuit for CA3191E and CA3192E. (Cont'd from page 6).

If only one polarity AFT output is required, the other IC terminal (12 or 13) may be grounded and its associated components can be deleted.

The dc gain of the AFT amplifier can be increased by reducing the value of the 91-k resistor connected to terminal 9 (i.e. increase the input current to the current mirror D6, Q27). Reducing the value to 47k will increase the gain about 6 dB but the dc

offset between terminals 12 and 13 will also increase.

The AFT may be disabled by opening or preferably grounding terminal 9. The dc voltage at terminals 12 and 13 will be about 6 V if the 47-k resistors are matched and point B is 12 Volts.

Terminal 11 voltage supply may be increased to 24 V maximum if higher ampli-

tude AFT output swings are desired at terminals 12 and 13. If the voltage at terminal 11 is increased to 24 volts, the four 47k resistors shown by terminals 12 and 13 should be increased to 100k each.

In the layout of the circuit board incorporating a CA3192E, care should be taken to insure that the video output circuits connected to terminal 8 are not in proximity to or coupled to the input terminals 3 and 5.

The input signal at terminal 3 should be about 30 millivolts.

Terminal 4 (+Vs) should be bypassed with a 1000-picofarad and a 10-microfarad capacitor having the shortest possible leads.

The 22-picofarad capacitor at terminal 5 should be connected to terminal 6 with very short leads to reduce FM pickup.

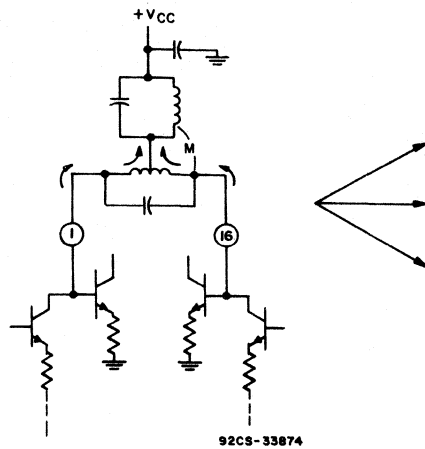
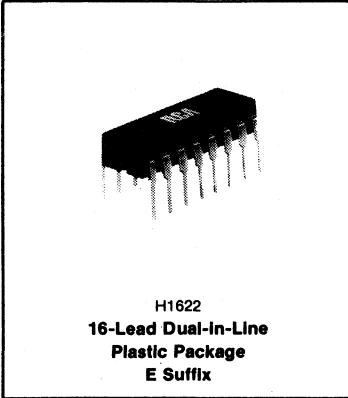


Fig. 5 - CA3192E with discriminator transformer.

CA7607E, CA7611E



Video IF Amplifier System for Color and Black and White TV Receivers

Especially Suitable for SAW Filter Applications

FEATURES

- High-gain wideband IF output
- Excellent S/N ratio
- Excellent DG/DP characteristics
- Black and white noise inverters
- Peak AGC
- Fast uniform AGC action
- Wide-gain reduction range
- Synchronous AFT detector
- High gain AFT
- Synchronous video detector
- Negative video output
- VTR switch

RCA CA7607 and CA7611* perform video IF amplification, video detection and amplification, AFT detection and amplification and AGC control of video IF and tuner stages. The CA7607 is suitable for FET applications; the CA7611 is used for NPN tuner stages and has a higher value of RF AGC control current.

A three-stage, wide-band IF amplifier employs an advanced gain reduction circuit for a wide range of AGC gain control with excellent stability at all gain conditions.

A synchronous video demodulator having a low distortion reference amplifier provides a negative-polarity video output signal containing negligible intermodulation products.

Noise inverters prevent ultra white and black spots in the picture.

A separate synchronous demodulator is used for AFT detection giving an accurate and sensitive AFT (12 kHz/V typ.).

A VTR switch permits removing internal video when using a VTR.

The CA7607E and CA7611E are supplied in a 16-lead dual-in-line plastic package.

*The CA7607E was formerly RCA Dev. No. TA10770; the CA7611E was formerly RCA Dev. No. TA11025.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE:	
Between Terminals 11-13	15 V
Between Terminals 4-13	15 V
VIDEO OUTPUT CURRENT; I12	6 mA
DEVICE DISSIPATION:	
Up to TA = 70°C	890 mW
Above TA = 70°C	Derate linearly 11.2 mW/°C
AMBIENT TEMPERATURE RANGE:	
Operating	-40 to +70° C
Storage	-65 to +150° C

TV/CATV Circuits

CA7607E, CA7611E

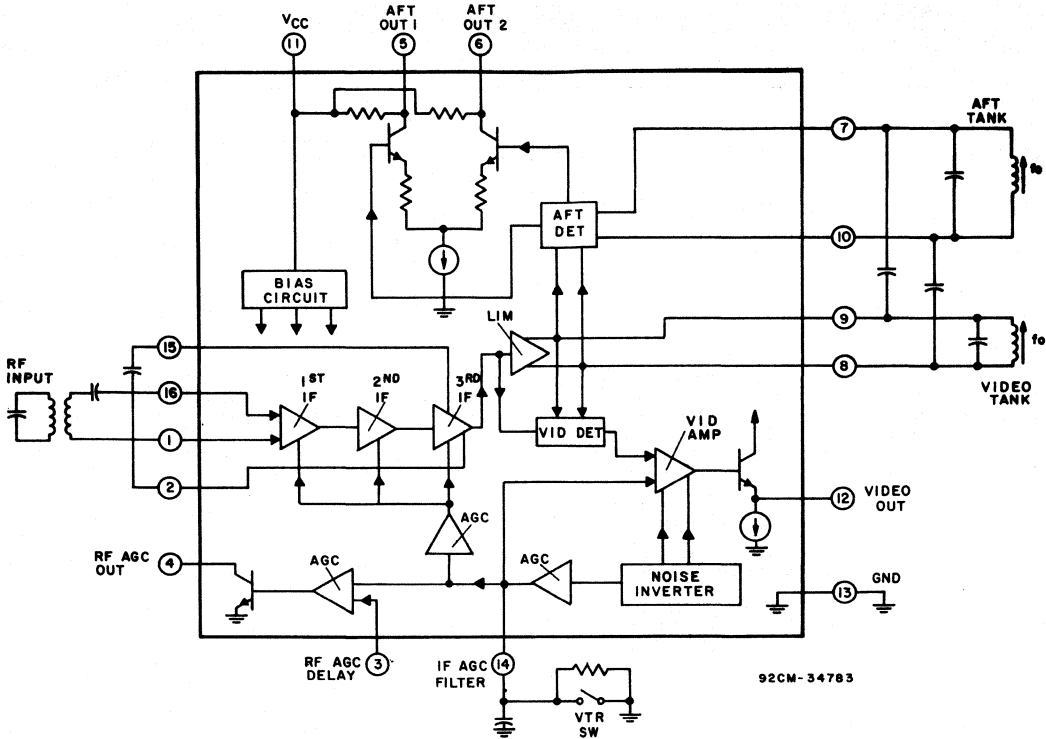


Fig. 1 — Block diagram of the CA7607E and CA7611E.

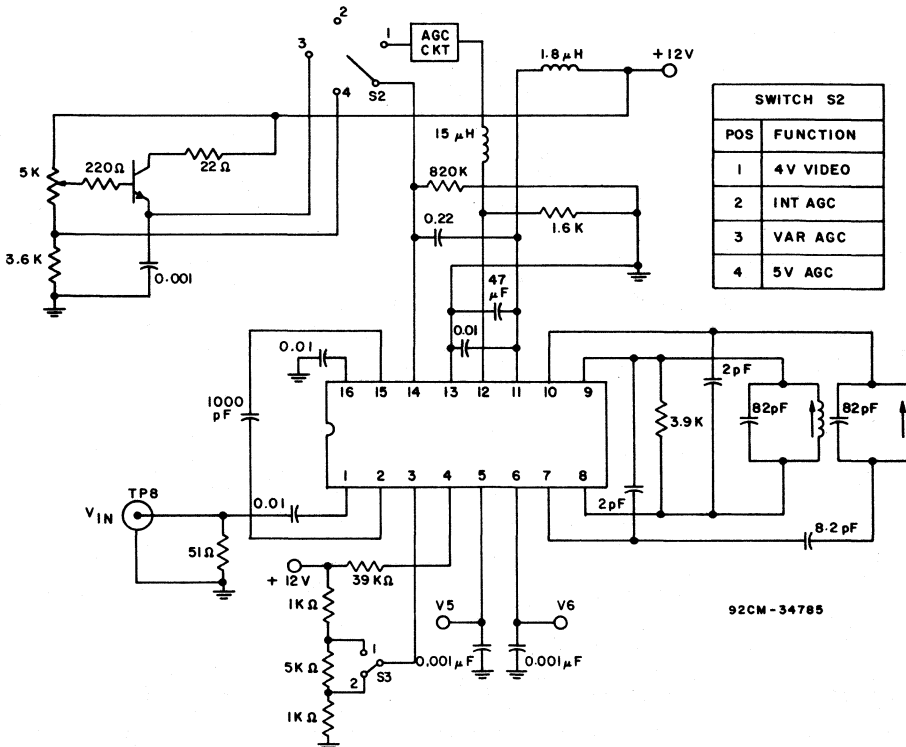


Fig. 2 — Typical application circuit for the CA7607E and CA7611E.

Linear Integrated Circuits

CA7607E, CA7611E

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V_+ = 12\text{ V}$, V_{IN} at TP8 (Fig. 3)

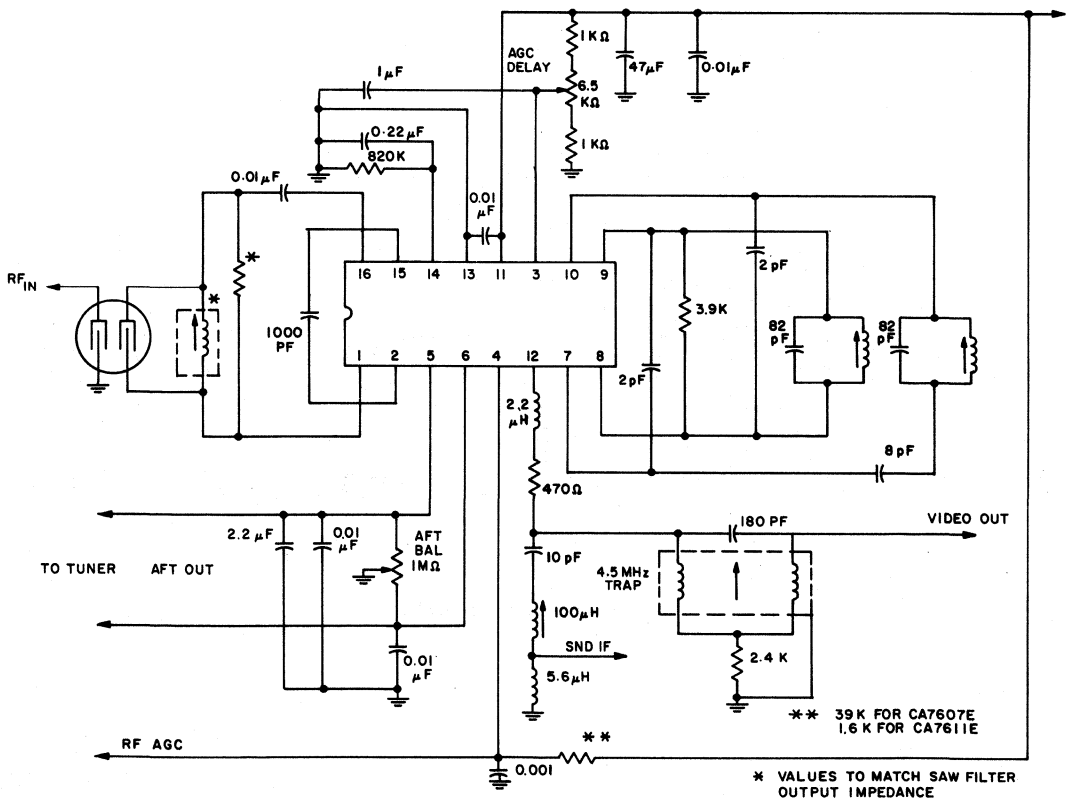
CHARACTERISTIC	TEST CONDITIONS	S2	S3	LIMITS			UNITS
				MIN.	TYP.	MAX.	
Supply Current I12	$V_{IN} = 0$	4	1	42.0	51.0	63.0	mA
Video DC Output Voltage V12	$V_{IN} = 0$	4	1	5.2	5.5	5.8	VDC
AFT DC Output Voltage V5	$V_{IN} = 0$	4	1	5.3	6.8	8.3	VDC
AFT DC Output Voltage V6	$V_{IN} = 0$	4	1	5.3	6.8	8.3	VDC
AFT Output Offset Voltage V5-V6	$V_{IN} = 0$	4	1	-1.5	0.0	1.5	VDC
RF AGC Residual Output Voltage V4 SAT	CA7607E	4	1	0.0	0.2	0.5	VDC
	CA7611E	4	2				
RF AGC Voltage Drop V11-V4	CA7607E	2	2	-0.1	0.0	0.1	VDC
	CA7611E	4	1				
Maximum Video Sensitivity V12	$V_{IN} = 25\ \mu\text{Vrms CW}$	2	2	-0.25	0.25	1.0	VDC
Minimum Video Sensitivity V12	$V_{IN} = 85\ \mu\text{Vrms CW}$	2	2	1.0	2.0	3.8	VDC
Synch Tip Level Voltage V12	$V_{IN} = 15\ \text{mVrms}$	2	2	2.3	2.5	2.7	VDC
Black Noise Threshold Level Voltage V12	$V_{IN} = 50\ \text{mVrms } 45.75\ \text{MHz}$ @ 30% AM MOD 1kHz	3	2	1.4	1.6	1.8	VDC
Black Noise Clamp Level V12		3	2	2.9	3.3	3.7	VDC
White Noise Threshold Level V12	$V_{IN} = 60\ \text{mVrms } 52\ \text{MHz}$ @ 30% AM MOD 1kHz	3	2	6.0	6.4	6.8	VDC
White Noise Clamp Level V12		3	2	3.7	4.1	4.5	VDC
Video Freq. Response at 3.58 MHz V12		1	2	-2	0	+1	dB
Video Freq. Response @ 4.5 MHz V12		1	2	-3	-2	+2	dB
920 kHz Beat V12	$V_{IN1} = 33\ \text{mVrms CW}$ $V_{IN2} = 11\ \text{mVrms CW}$ $V_{IN3} = 11\ \text{mVrms CW}$	1	2	31	38	—	dB
Video Amplifier Bandwidth V12 +BW		1	2	4.5	5.5	10.0	MHz
Suppression of Carrier V12	$V_{IN} = 25\ \text{mV } 45.75\ \text{MHz}$ @ 80% AM MOD. 1 kHz	3	2	40	50	—	dB
Suppression of 2nd Harmonic V12		3	2	35	50	—	dB
Differential Phase V12		2	2	—	3.5	6.0	DEG
Differential Gain V12		2	2	—	7	10	%
Picture-to-Noise Ratio PIN12	$V_{IN} = 25\ \text{mV } 45.75\ \text{MHz CW}$	1	2	53	58	—	dB
Picture-to-Noise Ratio PIN12	$V_{IN} = 7.5\ \text{mV } 45.75\ \text{MHz CW}$	1	2	50	54	—	dB
AFT Sensitivity $\frac{\Delta f}{V5-V6}$	$V_{IN} = 15\ \text{mVrms CW}$	2	2	6.0	12.0	16.0	kHz/V
AFT Output @ 44.75 MHz V5	$V_{IN} = 15\ \text{mVrms CW}$	2	2	11.4	11.9	12.1	VDC
AFT Output @ 44.75 MHz V6	$V_{IN} = 15\ \text{mVrms CW}$	2	2	1.6	2.1	2.8	VDC

TV/CATV Circuits

CA7607E, CA7611E

ELECTRICAL CHARACTERISTICS (cont'd.)

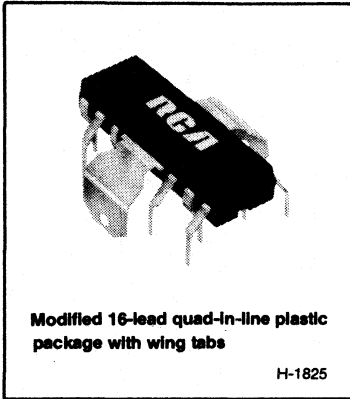
CHARACTERISTIC	TEST CONDITIONS	S2	S3	LIMITS			UNITS
				MIN.	TYP.	MAX.	
AFT Output @ 46.75 MHz V5	VIN = 15mVrms CW	2	2	1.6	2.1	2.8	VDC
AFT Output @ 46.75 MHz V6	VIN = 15 mVrms CW	2	2	11.4	11.9	12.1	VDC
RF Delay 1 V4	VIN = 15mVrms 45.75 MHz CW CA7607E CA7611E	2 2	1 2	0.0	1.0	10.4	VDC
RF Delay 2 V4	VIN = 100mVrms 45.75 MHz CW CA7607E CA7611E	2 2	2 1	10.6	12.0	12.1	VDC
RF AGC Leakage Current I4L				—	—	1.0	μA
Maximum Available Current I4MAX	CA7607E CA7611E			0.3 7.0			mA
RF Delay LO V4	CA7607E CA7611E	2 2	1 2	0.2	5.0	15.0	mV
RF Delay HI V4	CA7607E CA7611E	2 2	2 1	100	200	1000	mV
Input Impedance PIN 1-16		4		—	3.0 3.0	—	kΩ pF



92CL-34784

Fig. 3 — Test circuit for the CA7607E and CA7611E.

CA1190



TV Sound IF and Audio Output Subsystems

Features:

- Nominal power output: 4 W at $V^+ = 24$ V, $R_L = 16 \Omega$, dist. = 10%, 2 W at $V^+ = 12$ V, $R_L = 8 \Omega$, dist. = 10%
- Wide power-supply range: 9 to 28 V
- Low quiescent current: 25 mA typ.
- 5-kHz deviation sensitivity: 1 W output typ.
- 3-dB limiting sensitivity: 50 μ V typ.
- Excellent AM rejection: 50 dB typ.
- Differential peak detector - requires one tuned coil
- Electronic volume control with improved taper and single wire control

The RCA-CA1190Q combines sound IF and audio output subsystems on a single monolithic integrated circuit to provide a television sound system. Each device includes a multistage IF amplifier-limiter, an FM detector, and an audio power amplifier that is designed to drive, primarily, an 8- 16-, or 32-ohm speaker.

The CA1190Q is electrically and mechanically equivalent to industry type TDA1190Z.

The CA1190Q differs from the TDA1190Z in that it includes provisions for a lower value volume control.

The CA1190Q is supplied in the 16-lead quad-in-line plastic package having an integral bent-down wing-tab (Q-suffix) heat sink intended for PC board mounting.

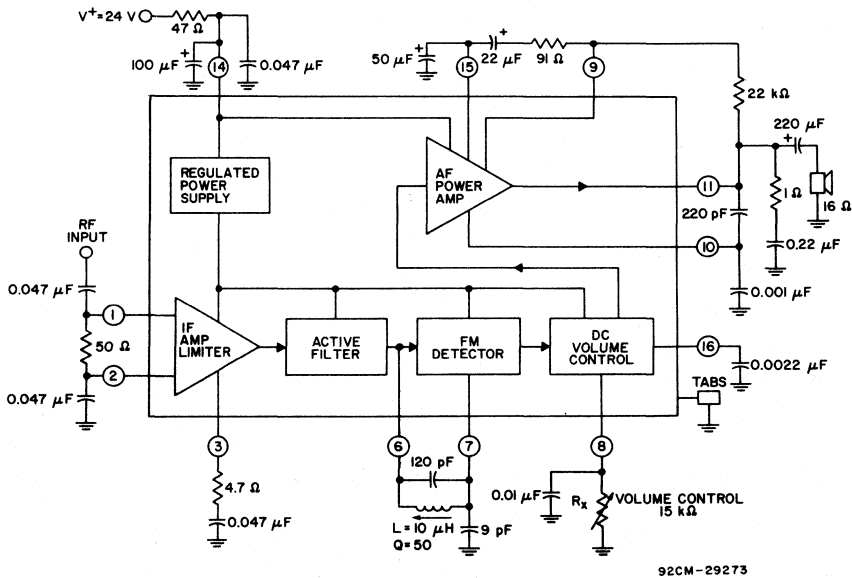


Fig. 1 - CA1190Q typical application.

MAXIMUM RATINGS, Absolute-Maximum Values:

		UNITS
DC SUPPLY-VOLTAGE (Between Term. 14 V+ and ground tabs)	+28	V
OUTPUT PEAK CURRENT:		
Repetitive	1.5	A
Non-repetitive	2	A
INPUT SIGNAL VOLTAGE (Between Terms. 1 and 2)	±3	V
DEVICE DISSIPATION:		
With Infinite Heat Sink —		
Up to $T_A = 90^\circ\text{C}$	5	W
Above $T_A = 90^\circ\text{C}$	83.3	mW/°C
derate linearly		
With No Heat Sink — (free air) —		
Up to $T_A = 25^\circ\text{C}$	1.75	W
Above $T_A = 25^\circ\text{C}$	14	mW/°C
derate linearly		
THERMAL RESISTANCE:		
Junction to ground tabs	12	°C/W
Junction to ambient	70	°C/W
AMBIENT TEMPERATURE RANGE:		
Operating	-40 to +85	°C
Storage	-65 to +150	°C
LEAD TEMPERATURE (During Soldering):		
At a distance 1/16 in. ± 1/32 in. (1.59 ± 0.79 mm) from case for 10 seconds max.	+265	°C

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V_+ = 24\text{ V}$, DC Volume Control $R_X = 0\ \Omega$, $R_L = 16\ \Omega$ unless otherwise indicated. Refer to Fig. 1.

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
Static Characteristics					
Current into Term. 14	$P_O = 0$	10	25	40	mA
Dynamic Characteristics					
IF Amplifier: Input Limiting Voltage, (At - 3 dB point), V_1 (lim)	$f_O = 4.5\text{ MHz}$, $f_M = 400\text{ Hz}$ $\Delta f = \pm 25\text{ kHz}$	—	50	100	μV
AM Rejection, AMR	$f_O = 4.5\text{ MHz}$, $f_M = 400\text{ Hz}$, Modulation Index = 0.3, $V_{IN} = 1\text{ mV}$	40	50	—	dB
Deviation Sensitivity	$f_O = 4.5\text{ MHz}$, $f_M = 400\text{ Hz}$ $\Delta f = \pm 25\text{ kHz}$, $V_I = 1\text{ mV}$ $R_X = 0$, Deviation necessary to obtain 4 Vrms across 16 Ω (1 W)	—	5	—	kHz
Minimum Audio Output	$f_O = 4.5\text{ MHz}$, $f_M = 400\text{ Hz}$ $\Delta f = \pm 25\text{ kHz}$, $V_I = 1\text{ mV}$ $R_X = 15\text{ k}\Omega$	—	—	10	mVrms
Distortion at $P_O = 1.5\text{ W}$	$f_O = 4.5\text{ MHz}$, $f_M = 400\text{ Hz}$ $\Delta f = \pm 25\text{ kHz}$, $V_{IN} = 1\text{ mV}$	—	—	3	%
Signal to Noise Ratio	V_{out} at $\Delta f = 0$ with R_X adjusted for $V_{out} = 4\text{ Vrms}$ at $\Delta f = \pm 25\text{ kHz}$	50	—	—	dB

Linear Integrated Circuits

CA1190

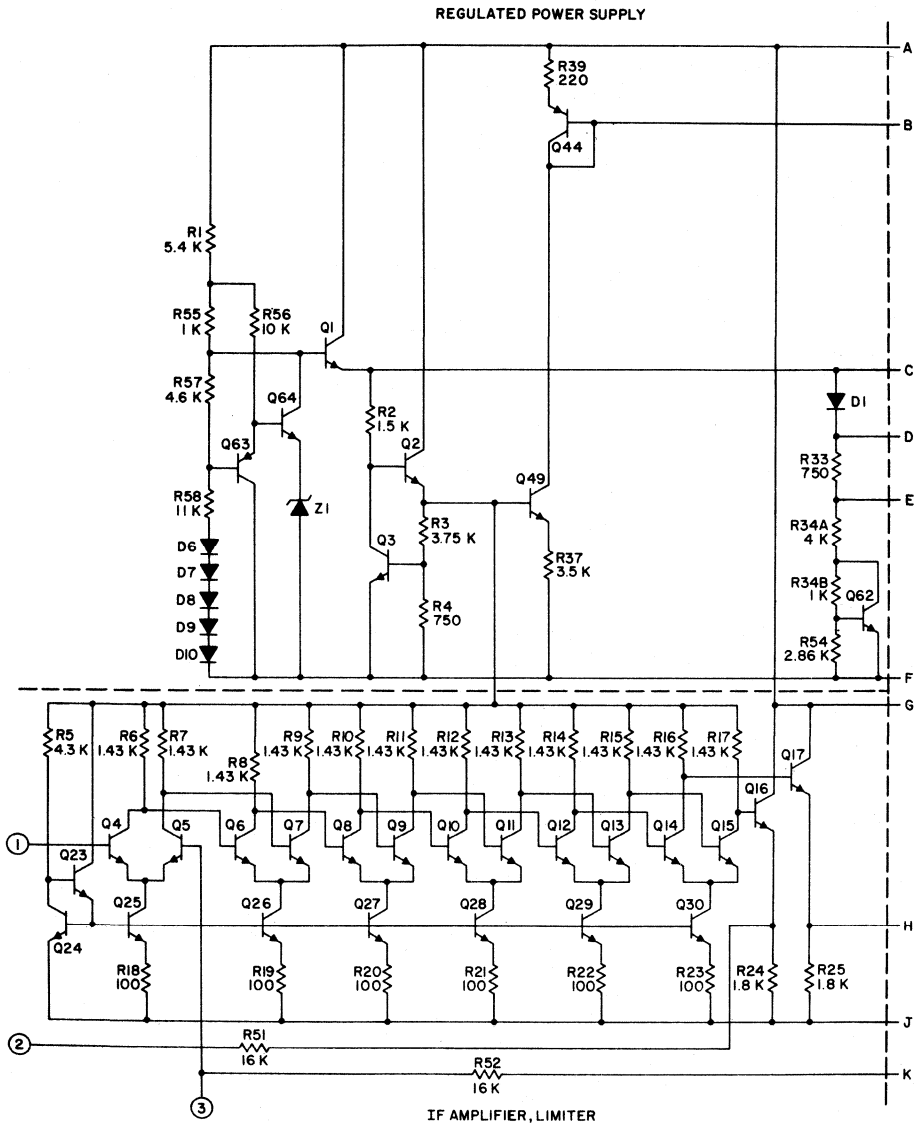
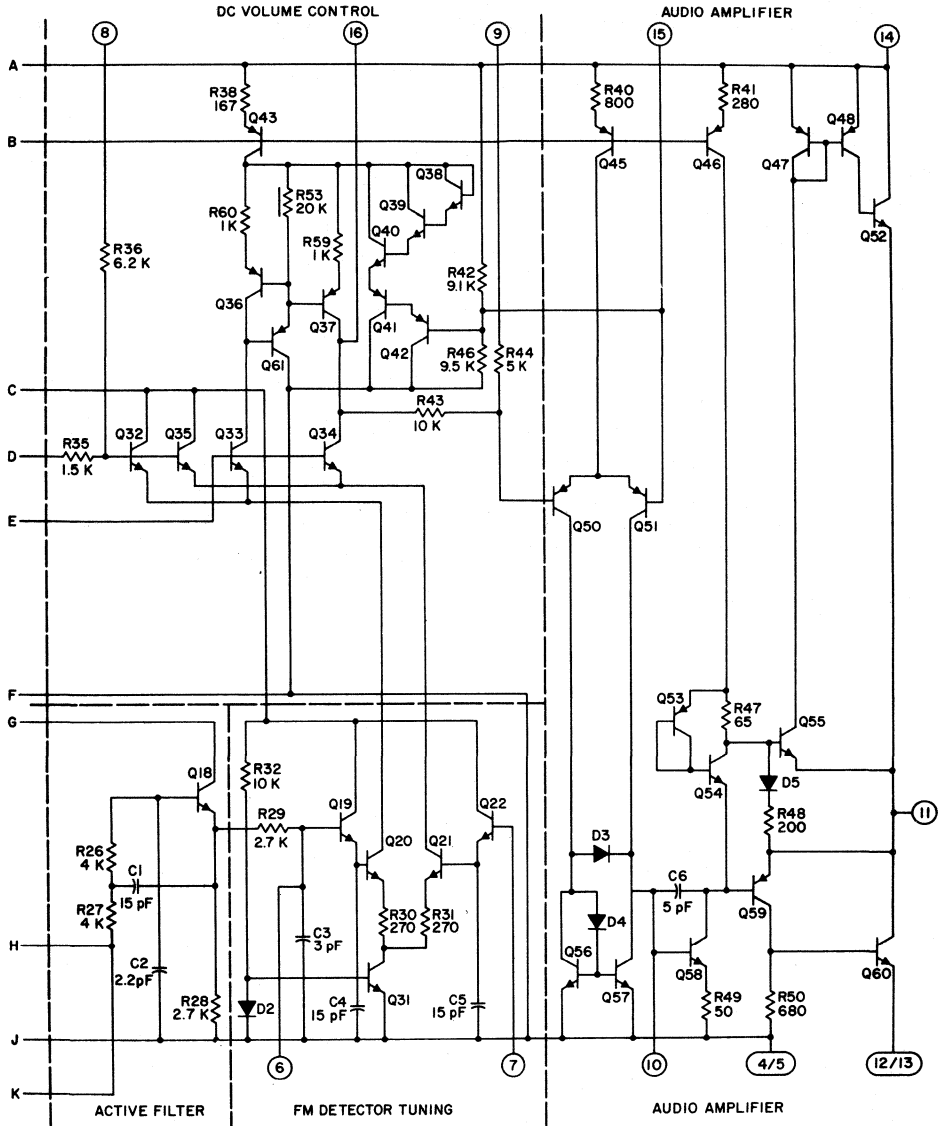
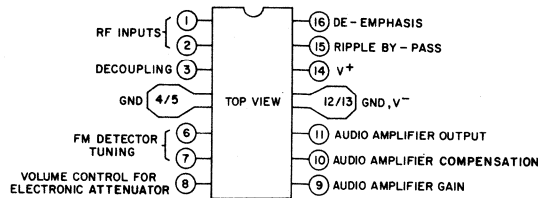


Fig. 2 - CA1190Q (cont'd on next page).



92CL-29274

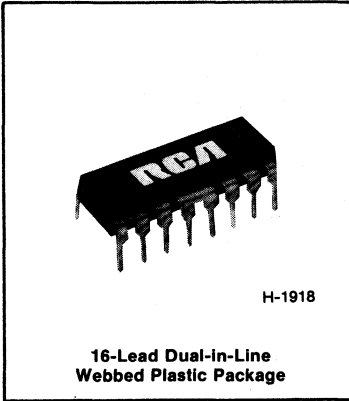
Fig. 2 - CA1190Q (cont'd from previous page).



92CS-29272

Fig. 3 - Terminal diagram.

CA1191



TV Sound IF and Audio Output Subsystems

Features:

- Nominal power output: 4 W at $V_+ = 24$ V, $R_L = 16 \Omega$, dist. = 10%, 2 W at $V_+ = 12$ V, $R_L = 8 \Omega$ dist. = 10%
- Wide power-supply range: 9 to 28 V
- Low quiescent current: 25 mA typ.
- 5-kHz deviation sensitivity: 1 W output typ.
- 3-dB limiting sensitivity: 50 μ V typ.
- Excellent AM rejection: 50 dB typ.
- Differential peak detector - requires one tuned coil
- Electronic volume control with improved taper and single wire control

The RCA-CA1191E* combines sound IF and audio output subsystems on a single monolithic integrated circuit to provide a television sound system. Each device includes a multi-stage IF amplifier-limiter, an FM detector, and an audio power amplifier that is designed to drive, primarily, an 8-, 16, or 32 ohm speaker.

The CA1191E is electrically and mechanically equivalent to industry type TDA 3190.

*Formerly RCA Dev. No. TA11029

The CA1191E differs from the TDA3190 in that it includes provisions for a lower value volume control.

The CA1191E is supplied in the dual-in-line 16 lead plastic package with webbed-lead construction for improved dissipation and allows the use of a standard IC socket or printed circuit board layout.

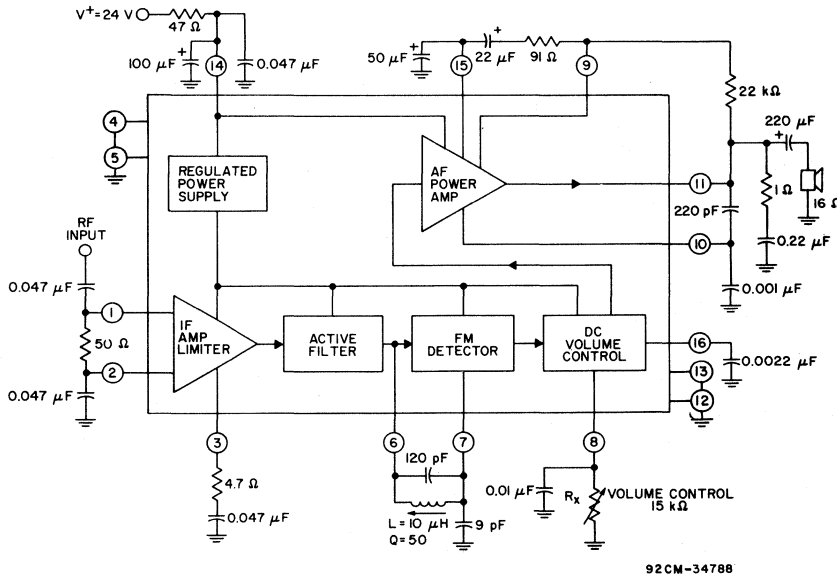


Fig. 1 — Block diagram of the CA1191E in a typical application.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE (Between Term. 14 V ⁺ and ground tabs)	+28	V
OUTPUT PEAK CURRENT:		
Repetitive	1.5	A
Non-repetitive	2	A
INPUT SIGNAL VOLTAGE (Between Terms. 1 and 2)	±3	V
DEVICE DISSIPATION:		
With Infinite Heat Sink —		
Up to T _A = 90°C	4.3	W
Above T _A = 90°C..... derate linearly	71.7	mW/°C
With No Heat Sink — (free air) —		
Up to T _A = 25°C	1.6	W
Above T _A = 25°C..... derate linearly	12.8	mW/°C
THERMAL RESISTANCE:		
Junction to ground pins	14	°C/W
Junction to ambient	80	°C/W
AMBIENT TEMPERATURE RANGE:		
Operating	-40 to +85	°C
Storage	-65 to +150	°C
LEAD TEMPERATURE (During Soldering):		
At a distance 1/16 in. ± 1/32 in. (1.59 ± 0.79 mm) from case for 10 seconds max.	+265	°C

ELECTRICAL CHARACTERISTICS at T_A = 25°C, V⁺ = 24 V, DC Volume Control R_x = 0 Ω, R_L = 16 Ω unless otherwise indicated. Refer to Fig. 1.

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		MIN.	TYP.	MAX.	
Static Characteristics					
Current into Term. 14	P _o = 0	10	25	40	mA
Dynamic Characteristics					
IF Amplifier: Input Limiting Voltage, (At -3 dB point), V ₁ (lim)	f _o = 4.5 MHz, f _m = 400 Hz Δf = ± 25 kHz	—	50	100	μV
AM Rejection, AMR	f _o = 4.5 MHz, f _m = 400 Hz, M _o modulation Index = 0.3, V _{IN} = 1 mV	40	50	—	dB
Deviation Sensitivity	f _o = 4.5 MHz, f _m = 400 Hz Δf = ± 25 kHz, V ₁ = 1 mV R _x = 0, Deviation necessary to obtain 4 V _{rms} across 16 Ω (1 W)	—	5	—	kHz
Minimum Audio Output	f _o = 4.5 MHz, f _m = 400 Hz Δf = ± 25 kHz, V ₁ = 1 mV R _x = 15 kΩ	—	—	10	mV _{rms}
Distortion at P _o = 1.5 W	f _o = 4.5 MHz, f _m = 400 Hz Δf = ± 25 kHz, V _{IN} = 1 mV	—	—	3	%
Signal to Noise Ratio	V _{out} at Δf = 0 with R _x adjusted for V _{out} = 4 V _{rms} at Δf = ± 25 kHz	50	—	—	dB

Linear Integrated Circuits

CA1191

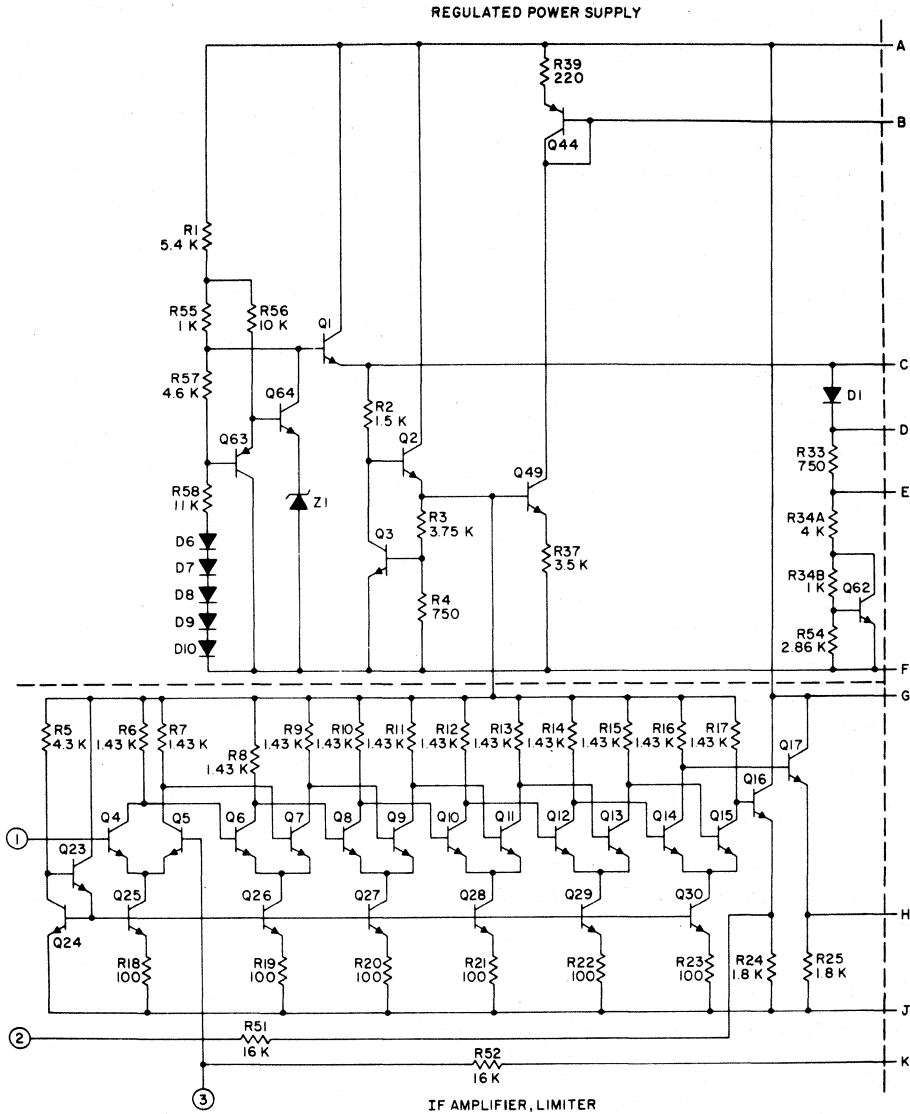
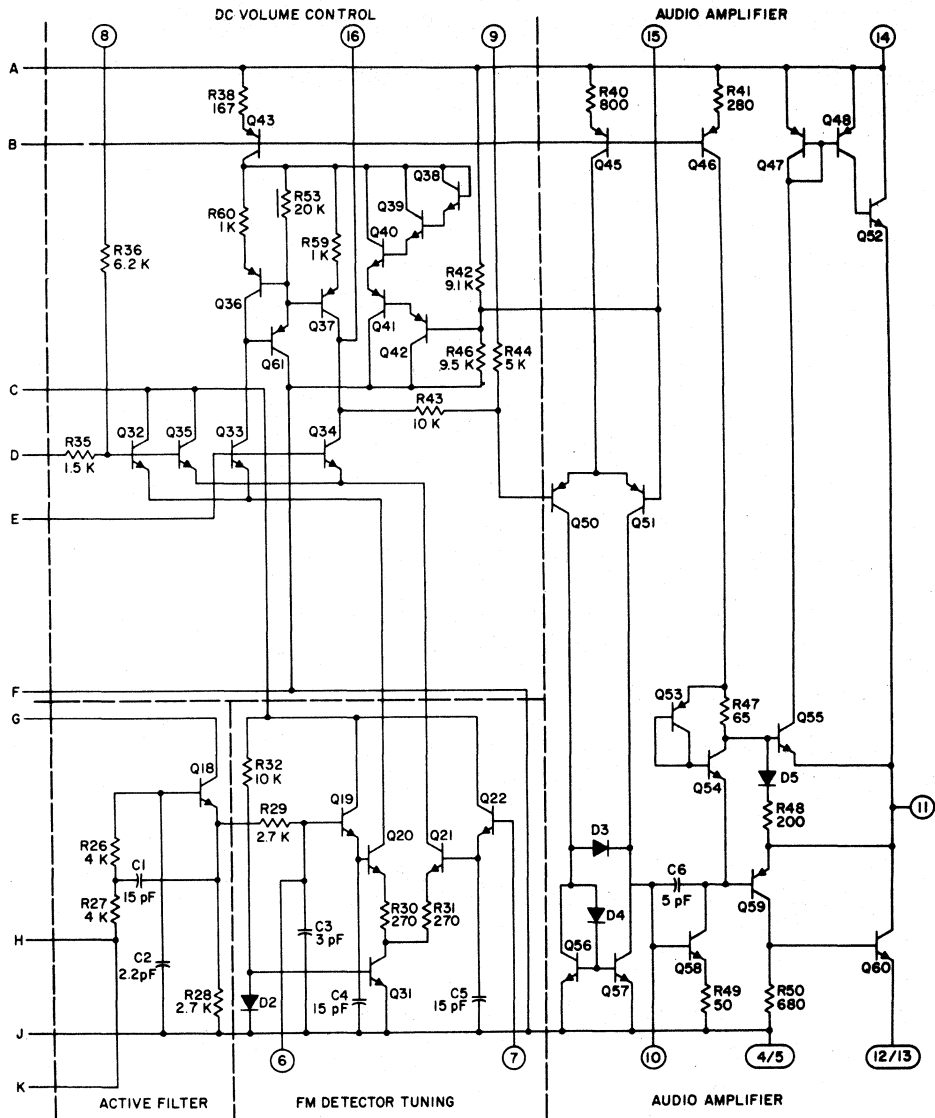


Fig. 2 — CA1191E Schematic diagram.

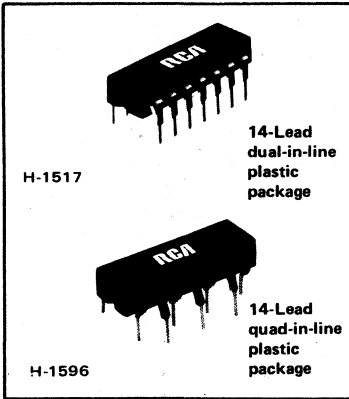
TV/CATV Circuits CA1191



92CL-29274

CA1191E Schematic diagram (con't.)

CA2111AE, CA2111AQ



FM IF Amplifier-Limiter and Quadrature Detector

For FM IF and TV Sound IF Applications

Features:

- Direct replacement for ULN2111A and MC1357
- Good sensitivity: Input limiting voltage (knee) (400 μ V typ. at 10.7 MHz; 250 μ V typ. at 4.5 MHz and 5.5 MHz)
- Excellent AM rejection (45 dB typ. at 10.7 MHz)
- Provision for output from 3-stage IF amplifier section
- Low harmonic distortion
- Quadrature detection permits simplified single-coil tuning
- Extremely low AFC voltage drift over full operating-temperature range
- Minimum number of external parts required

The CA2111A, on a single monolithic chip, provides a multi-stage wideband amplifier-limiter, a quadrature detector, and an emitter-follower output stage. This device is designed for use in FM receivers and in the sound IF sections of TV receivers. In addition, an output terminal is provided which allows the use of the amplifier-limiter as a straight 60-dB wideband amplifier.

The amplifier-limiter features the excellent limiting characteristics of 3 cascaded differential amplifiers.

The quadrature detector requires only one coil in the associated outboard circuit and therefore, tuning is a simple procedure.

A unique feature of the CA2111A is its exceptionally low AFC voltage drift over the full operating-temperature range.

This device can be supplied in either dual-in-line or quad-in-line 14-lead plastic packages (CA2111AE and CA2111AQ, respectively).

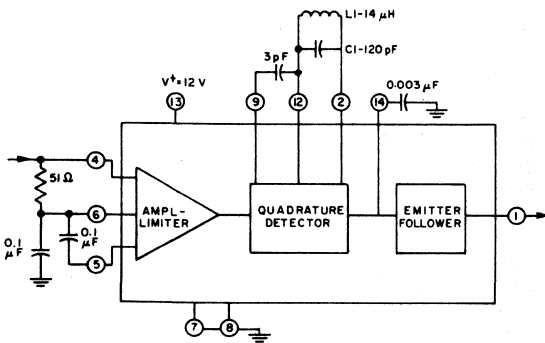


Fig. 1—Block diagram of CA2111A and associated outboard components.

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A=25^\circ C$

DC Supply Voltage [between terminals 5 (V^+) and 3 (V^-)]	16	V
Device Dissipation:		
Up to $T_A = 60^\circ C$	600	mW
Above $T_A = 60^\circ C$	derate linearly 6.7 mW/ $^\circ C$	
Ambient Temperature Range:		
Operating	-55 to +125	$^\circ C$
Storage	-65 to +150	$^\circ C$
Lead Temperature (During Soldering):		
At distance 1/16 \pm 1/32 in. (1.59 \pm 0.79 mm)		
from case for 10s max.	+ 265	$^\circ C$

92CS-20769

CA2111AE, CA2111AQ

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	LIMITS			UNITS
			MIN.	TYP.	MAX.	
DC Voltage: At Terminal 1	V_1	$V^+ = 12\text{V}$ $= 8\text{V}$	—	5.4 3.7	—	V
At Terminals 4, 5, 6, 10 At Terminals 2, 12	$V_4, 5, 6, 10$ $V_2, 12$	$V^+ = 8\text{V}$	—	1.35 3.5	—	
DC Current (into Terminal 13) At $V^+ = 8\text{V}$ At $V^+ = 12\text{V}$	I_{13}		—	14 16	—	mA
Amplifier Input Resistance	R_4	$f_o = 10.7\text{ MHz}$	—	7	—	$k\Omega$
Amplifier Input Capacitance	C_4		—	11	—	pF
Detector Input Resistance	R_{12}		—	70	—	$k\Omega$
Detector Input Capacitance	C_{12}		—	2.7	—	pF
Amplifier Output Resistance	R_{10}		—	60	—	Ω
Detector Output Resistance	R_1		—	200	—	Ω
De-Emphasis Resistance	R_{14}		—	8.8	—	$k\Omega$

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

FM Modulation Frequency = 400 Hz, Source Resistance = 50Ω

CHARACTERISTIC	SYMBOL	TEST CONDITIONS								UNITS	TEST CIR- CUIT OR CHARAC- TERISTIC CURVES FIG. NO.
		$f_o = 10.7\text{ MHz}$ $\Delta f = \pm 75\text{ KHz}$		$f_o = 4.5\text{ MHz}$ $\Delta f = \pm 25\text{ KHz}$		$f_o = 5.5\text{ MHz}$ $\Delta f = \pm 50\text{ KHz}$		TYP.	MAX.		
		$V^+ = 12\text{V}$	$V^+ = 8\text{V}$	$V^+ = 12\text{V}$	$V^+ = 12\text{V}$						
LIMITS											
		TYP.	MAX.	TYP.	MAX.	TYP.	MAX.	TYP.	MAX.		
AMPL-LIMITER Input Limiting Threshold Voltage	$V_i(\text{lim})$ (4)	400	600	400	600	250	400	250	400	V (RMS)	3, 7, 8, 9
AM Rejection [‡] *	AMR(1)	45	—	37	—	36	—	40	—	dB	3, 4, 5, 6
Ampl. Voltage Gain \blacktriangle	$A_V(10)$	55	—	55	—	60	—	60	—	dB	3
DETECTOR Recovered Audio [‡] Output Voltage	$V_o(\text{AF})$ (1)	0.48	—	0.3	—	0.72	—	1.2	—	V (RMS)	3, 7, 8, 9
Total Harmonic [‡] Distortion	THD(1)	1	—	1	—	1.5	—	3	—	%	3

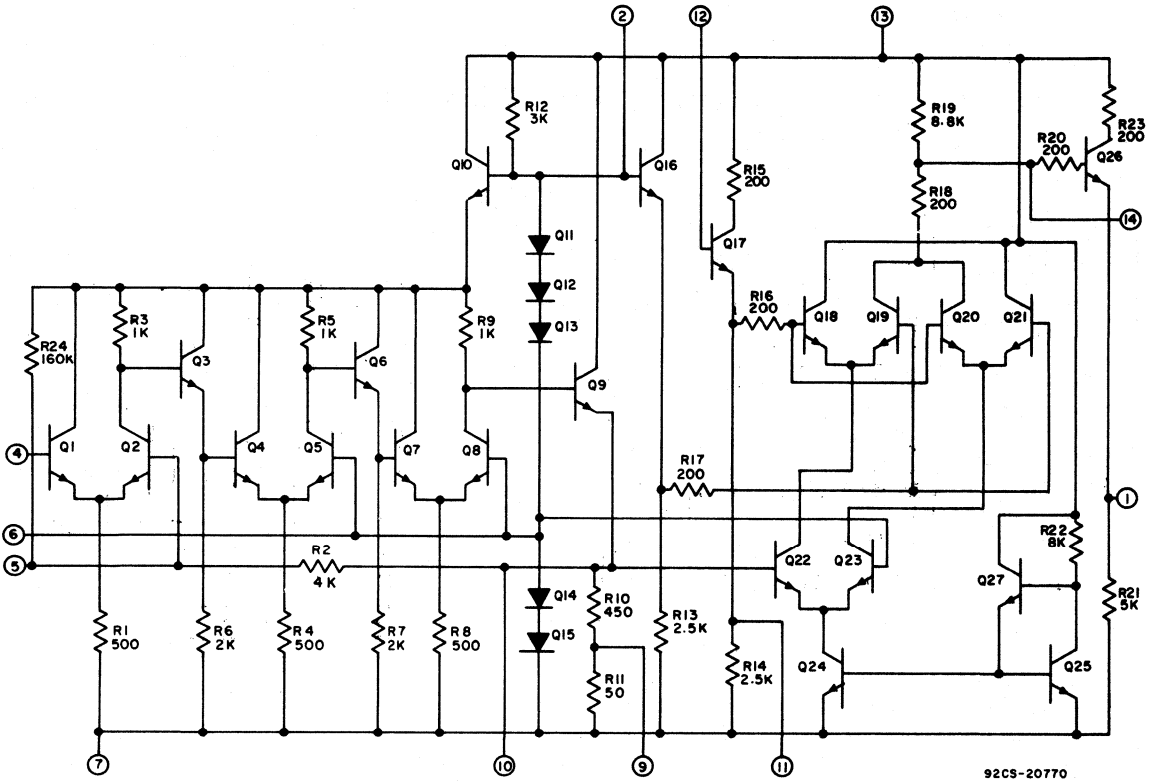
[‡] $V_i = 10\text{ mV (RMS)}$

$\blacktriangle V_i \leq 50\ \mu\text{V (rms)}$

*100% FM, 30% AM

Linear Integrated Circuits

CA2111AE, CA2111AQ

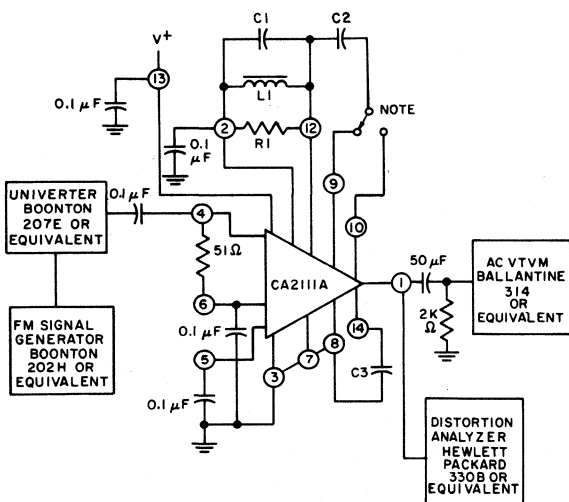


92CS-20770

Fig. 2—Circuit schematic—CA2111A

NOTE:

Input to the quadrature coil can be from either terminal 9 or terminal 10. Terminal 9 is normally used because it lessens the possibility of overloads during tuning. The use of terminal 10 increases the limiting sensitivity significantly and has been used successfully in these tests.



92CS-20771

COMPONENT VALUES							DETECTOR TRANSFER CHARACTERISTICS	
f	L ₁	C ₁	R ₁	Q	C ₂	C ₃	UPPER PEAK	LOWER PEAK
MHz	μH	pF	KΩ	-	pF	μF	MHz	MHz
4.5	14	120	20	30	3	0.003	4.98	4.42
5.5	8	100	20	30	3	0.003	5.63	5.37
10.7	2	120	3.9	20	4.7	0.01	10.9	10.5

Fig. 3—Test circuit.

CA2111AE, CA2111AQ

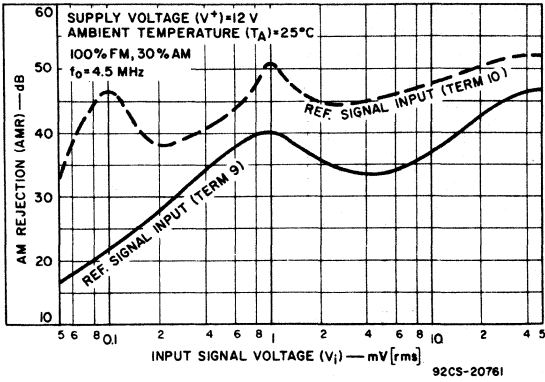


Fig. 4—AM rejection vs input voltage (4.5 MHz).

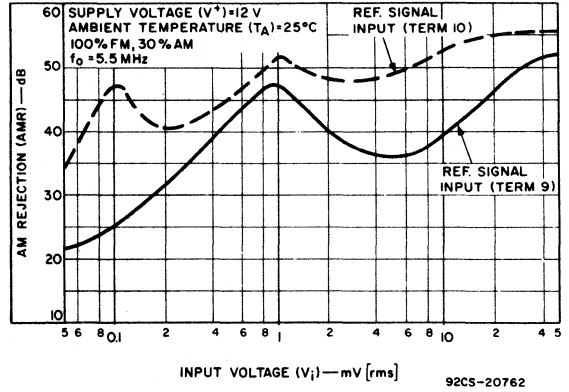


Fig. 5—AM rejection vs input voltage (5.5 MHz).

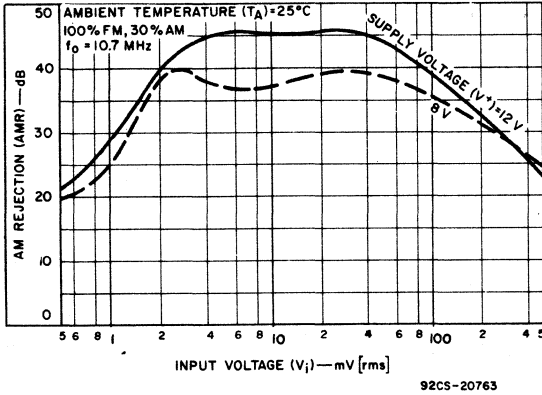


Fig. 6—AM rejection vs input voltage (10.7 MHz).

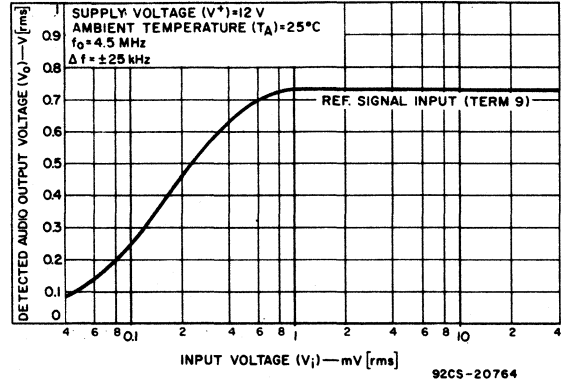


Fig. 7—Detected audio output vs input voltage (4.5 MHz).

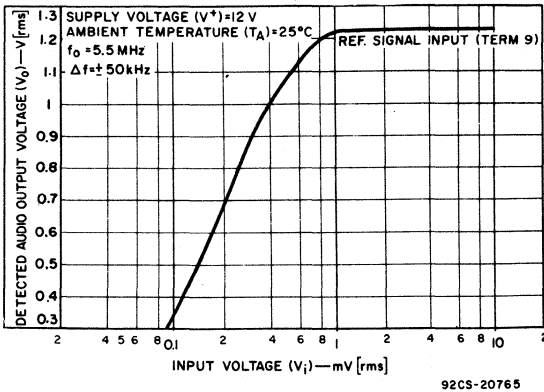


Fig. 8—Detected audio output vs input voltage (5.5 MHz).

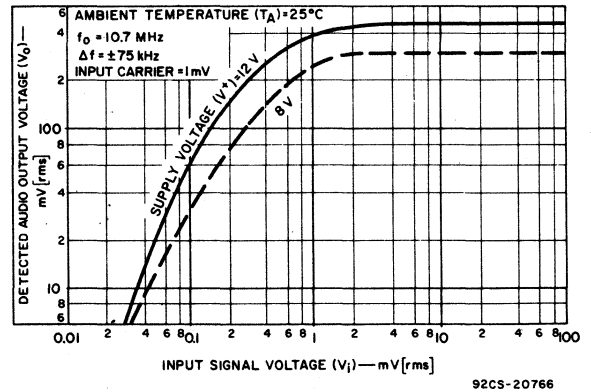


Fig. 9—Detected audio output voltage vs input voltage (10.7 MHz).

CA2111AE, CA2111AQ

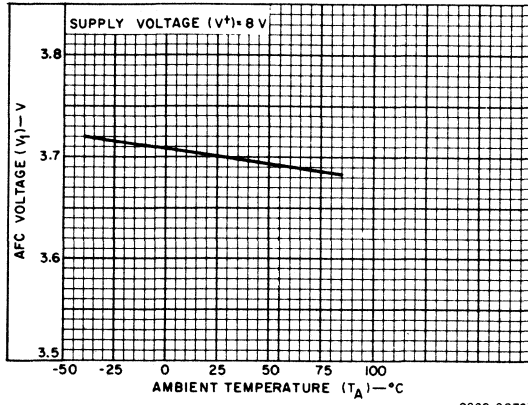


Fig. 10—AFC voltage vs ambient temp.

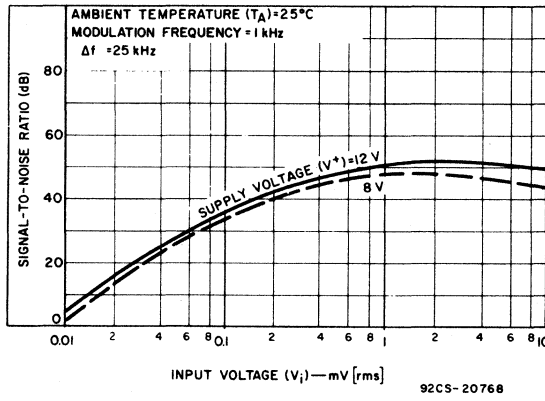
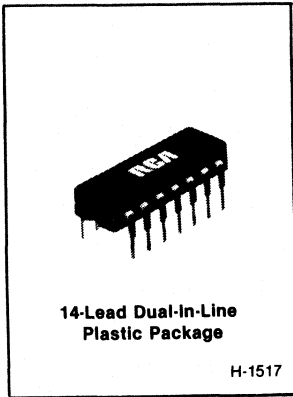


Fig. 11—Signal-to-noise ratio vs input voltage.



FM IF Amplifier-Limiter and Quadrature Detector

For FM IF and TV Sound IF Applications

Features:

- Direct replacement for ULN2136A and LM1841
- Good sensitivity: Input limiting voltage (knee) $400\ \mu\text{V}$ typ. at 10.7 MHz; $250\ \mu\text{V}$ typ. at 4.5 MHz and 5.5 MHz
- Excellent AM rejection (45 dB typ. at 10.7 MHz)
- Provision for output from 3-stage IF amplifier section

The CA2136A integrated circuit includes a multistage wideband amplifier-limiter, a quadrature detector, an emitter-follower output stage, and a voltage regulator on a single monolithic chip. This device provides a regulated supply voltage for the tuner stages in FM receivers. It can be used in any amplifier-limiter or FM demodulator application.

The amplifier-limiter features the excellent limiting characteristics of three cascaded differential amplifiers. The quadrature detector requires only one coil in the associated outboard circuit; tuning, therefore, is a simple procedure.

A unique feature of the CA2136A is its exceptionally low AFC voltage drift over the full operating-temperature range.

- Low harmonic distortion
- Quadrature detection permits simplified single-coil tuning
- Extremely low AFC voltage drift over full operating-temperature range
- Excellent line and load regulation
- Minimum number of external parts required
- Pin-compatible with the CA2111A

This device can be supplied in either dual-in-line or quad-in-line 14-lead plastic packages.

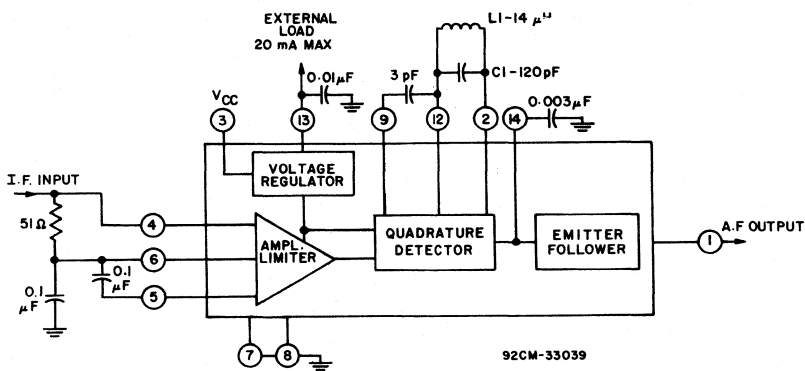


Fig. 1 - Block diagram of CA2136A and associated outboard components

Linear Integrated Circuits

CA2136A

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

DC SUPPLY VOLTAGE [Between Terminals 3 (V+) and 7 (V-)]	20 V
DEVICE DISSIPATION:	
Up to $T_A = 60^\circ\text{C}$	600 mW
Above $T_A = 60^\circ\text{C}$	Derate Linearly 6.7 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:	
Operating	-55 to +125 $^\circ\text{C}$
Storage	-65 to +150 $^\circ\text{C}$
EXTERNAL LOAD CURRENT	20 mA
LEAD TEMPERATURE (During Soldering):	
At distance 1/16 ± 1/32 in. (1.59 ± 0.79 mm) from case for 10 s max.	+265 $^\circ\text{C}$

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	LIMITS			UNITS
			Min.	Typ.	Max.	
DC Voltage:						
At Terminal 1	V_1	$V^+ = 12\text{ V}$	3.5	4.3	5.0	V
At Terminals 4, 5, 6, 10	$V_4, 5, 6, 10$	$V^+ = 12\text{ V}$	—	1.35	—	
At Terminals 2, 12	$V_2, 12$		—	3.8	—	
At Terminal 13	V_{13}		—	7.8	—	
DC Current (into Terminal 3) At $V^+ = 12\text{ V}$	I_3		—	21	—	mA
Amplifier Input Resistance	R_4	$f_o = 10.7\text{ MHz}$	—	7	—	k Ω
Amplifier Input Capacitance	C_4		—	11	—	pF
Detector Input Resistance	R_{12}		—	70	—	k Ω
Detector Input Capacitance	C_{12}		—	2.7	—	pF
Amplifier Output Resistance	R_{10}		—	60	—	Ω
Detector Output Resistance	R_1		—	200	—	Ω
De-Emphasis Resistance	R_{14}		—	10.5	—	k Ω

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

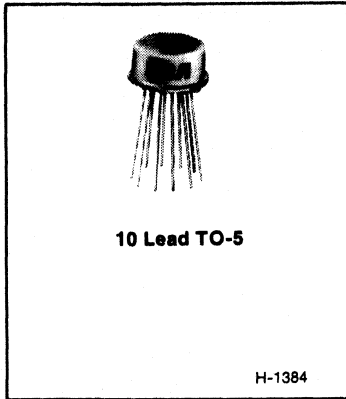
FM Modulation Frequency = 400 Hz, Source Resistance = 50 Ω

CHARACTERISTIC	SYMBOL	TEST CONDITIONS		UNITS	TEST CIR- CUIT OR CHARAC- TERISTIC CURVES FIG. NO.
		$f_o = 10.7\text{ MHz}$ $\Delta f = \pm 75\text{ kHz}$			
		$V^+ = 12\text{ V}$			
		LIMITS			
		Typ.	Max.		
AMPLIFIER-LIMITER					
Input Limiting Threshold Voltage	V_i (lim) (4)	400	600	μV (rms)	3
AM Rejection† *	AMR (1)	40	—	dB	3
Ampl. Voltage Gain▲	A_V (10)	53	—	dB	3
DETECTOR					
Recovered Audio‡ Output Voltage	V_o (AF) (1)	0.4	—	V (rms)	3
Total Harmonic‡ Distortion	THD (1)	1	3	%	3
Line Regulator	V_{reg}	5	10	mV/V	

† $V_i = 10\text{ mV}$ (rms)

▲ $V_i \leq 50\ \mu\text{V}$ (rms)

* 100% FM, 30% AM



Wide-Band Amplifiers

Features:

- Exceptionally high amplifier gain: power gain at 4.5 MHz/s - 75 dB typ.
- Excellent limiting characteristics - Input limiting voltage (k_{nee}) = 600 μ V typ. at 10.7 MHz/s
- Wide frequency capability - 100 kHz/s to > 20 MHz/s

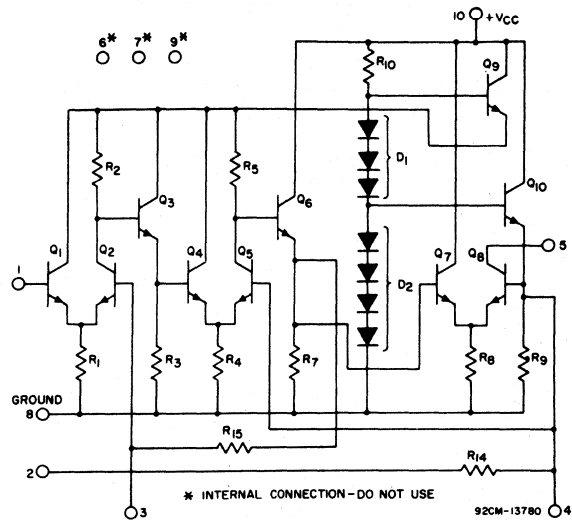


Fig. 1 - Schematic diagram for CA3011 and CA3012.

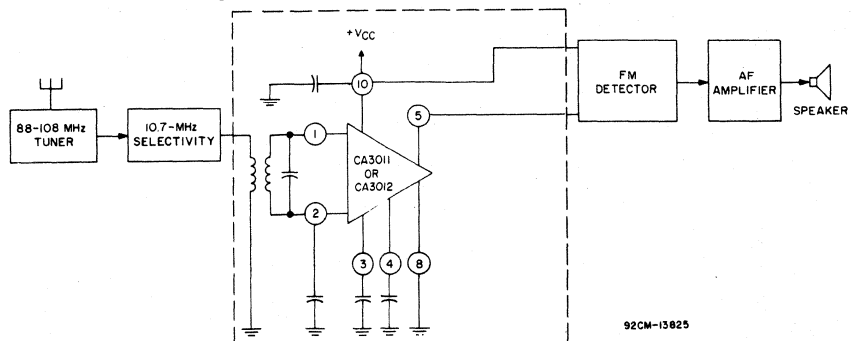


Fig. 2 - Block diagram of typical FM receiver using RCA-CA3011 or CA3012 integrated circuit wide-band amplifier.

Linear Integrated Circuits

CA3011, CA3012

ABSOLUTE-MAXIMUM VOLTAGE LIMITS AT $T_A = 25^\circ\text{C}$

Indicated voltage limits for each terminal can be applied under the specified voltage conditions for other terminals. All voltages are with respect to ground (Terminal 8).

NOTE: TERMINALS 6, 7, AND 9 OF RCA-CA3011 AND CA3012 ARE USED FOR INTERNAL CONNECTIONS. DO NOT APPLY VOLTAGES OR MAKE EXTERNAL CONNECTIONS TO THESE TERMINALS.

CA3011

TERMINAL	VOLTAGE LIMITS		VOLTAGE CONDITIONS AT OTHER TERMINALS						
			1	2	3	4	5	8	10
1	-3	+3	-	Same as 1	Do Not Apply External Voltage	+2.5 to +7.5	+7.5	Ground	+7.5
2	-3	+3	Same as 2	-		+2.5 to +7.5	+7.5	Ground	+7.5
3	-3	+3	-3 to +3	Same as 1		+2.5 to +7.5	+7.5	Ground	+7.5
4	+2.5	+7.5	-3 to +3	Same as 1		-	+7.5	Ground	+7.5
5	0	+10	-3 to +3	Same as 1		+2.5 to +7.5	-	Ground	+7.5
8	-3	+7.5	-3 to +3	Same as 1		+2.5 to +7.5	+7.5	Ground	+7.5
10	0	+10	-3 to +3	Same as 1		+2.5 to +7.5	+7.5	Ground	-
CASE	INTERNALLY CONNECTED TO TERMINAL NO.8 (GROUND TERMINAL)								

CA3012

TERMINAL	VOLTAGE LIMITS		VOLTAGE CONDITIONS AT OTHER TERMINALS						
			1	2	3	4	5	8	10
1	-3	+3	-	Same as 1	Do Not Apply External Voltage	+2.5 to +10	+10	Ground	+10
2	-3	+3	Same as 2	-		+2.5 to +10	+10	Ground	+10
3	-3	+3	-3 to +3	Same as 1		+2.5 to +10	+10	Ground	+10
4	+2.5	+10	-3 to +3	Same as 1		-	+10	Ground	+10
5	0	+13	-3 to +3	Same as 1		+2.5 to +10	-	Ground	+10
8	-3	+10	-3 to +3	Same as 1		+2.5 to +10	+10	Ground	+10
10	0	+13	-3 to +3	Same as 1		+2.5 to +10	+10	Ground	-
CASE	INTERNALLY CONNECTED TO TERMINAL NO.8 (GROUND TERMINAL)								

Example of Use of LIMITS TABLE:

OPERATING-TEMPERATURE RANGE -55 to $+125^\circ\text{C}$
 STORAGE-TEMPERATURE RANGE -65 to $+150^\circ\text{C}$

LEAD TEMPERATURE (During Soldering):
 At distance $1/16 \pm 1/32$ inch ($1.59 \pm 0.79\text{mm}$)
 from case for 10 seconds max. $+265^\circ\text{C}$

MAXIMUM INPUT-SIGNAL VOLTAGE:
 Between Terminals 1 and 2 $\pm 3\text{V}$

MAXIMUM DEVICE DISSIPATION 300 mW

RECOMMENDED MINIMUM DC SUPPLY VOLTAGE (V_{CC}) 5.5 V

For RCA-3012, a maximum voltage of ± 3 volts may be applied to Terminal 1 under the following conditions:

- Terminal 2 is at the same dc potential as Terminal 1
- Terminal 3: do not apply external voltage
- Terminal 4 is at any dc potential between +2.5 and +10 volts
- Terminal 5 is at a dc potential of +10 volts
- Terminals 6, 7, and 9 are at 0 dc potential (NOT USED)
- Terminal 8 is at dc ground potential
- Terminal 10 is at a dc potential of +10 volts

ELECTRICAL CHARACTERISTICS

CHARACTERISTICS (See Page 7 for Definitions of Terms)	SYMBOLS	TEST CONDITIONS				LIMITS						TYPICAL CHARAC- TERISTICS CURVES	
		SETUP & PROCEDURE	FREQUENCY f	DC SUPPLY VOLTAGE V _{CC}	AMBIENT TEMPER- TURE T _A	RCA CA3011			RCA CA3012				UNITS
						Fig.	Mc/s	Volts	°C	Min.	Typ.		
Total Device Dissipation*	P _T	3	-	6	-55	-	80	-	66	80	135	mW	4
					+25	60	90	133	66	90	121	mW	
					+125	-	70	-	65	70	121	mW	
		3	-	7.5	-55	-	130	-	97	130	190	mW	4
					+25	95	120	187	97	120	167	mW	
					+125	-	100	-	95	100	167	mW	
		3	-	10	-55	-	-	-	150	210	275	mW	4
					+25	-	-	-	150	190	255	mW	
					+125	-	-	-	150	160	255	mW	
Voltage Gain**	A	5	1	6	-55	-	55	-	50	55	-	dB	6
					+25	60	66	-	60	66	-	dB	
					+125	-	61	-	50	61	-	dB	
		5	1	7.5	-55	-	59	-	55	59	-	dB	6
					+25	65	70	-	65	70	-	dB	
					+125	-	65	-	55	65	-	dB	
		5	1	10	-55	-	-	-	55	61	-	dB	6
					+25	-	-	-	65	71	-	dB	
					+125	-	-	-	55	66	-	dB	
		5	4.5	7.5	+25	60	67	-	60	67	-	dB	7
					+25	55	61	-	55	61	-	dB	
		Input-Impedance Components: Parallel Input Resistance	R _{IN}	8	4.5	7.5	+25	-	3	-	-	3	-
C _{IN}	8		4.5	7.5	+25	-	7	-	-	7	-	pF	9
Output Impedance Components: Parallel Output Resistance	R _{OUT}	10	4.5	7.5	+25	-	31.5	-	-	31.5	-	kΩ	11
	C _{OUT}	10	4.5	7.5	+25	-	4.2	-	-	4.2	-	pF	11
Noise Figure	NF	12	4.5	7.5	+25	-	8.7	-	-	8.7	-	dB	13
Input Limiting Voltage (Knee)	V _{i(lim)}	5	4.5	7.5	+25	-	300	450	-	300	400	μV	6

* The total current drain may be determined by dividing P_T by V_{CC}.

** Recommended minimum dc supply voltage (V_{CC}) is 5.5 V. Nominal load current flowing into terminal 5 is 1.5 mA at 7.5 V.

CA3011, CA3012

TYPICAL CHARACTERISTICS AND TEST SETUPS

DISSIPATION TEST SETUP

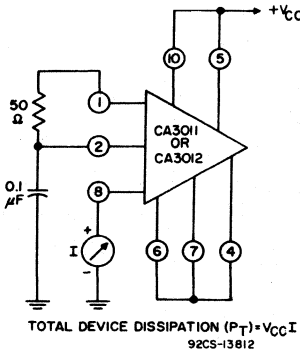


Fig. 3

DISSIPATION VS TEMPERATURE

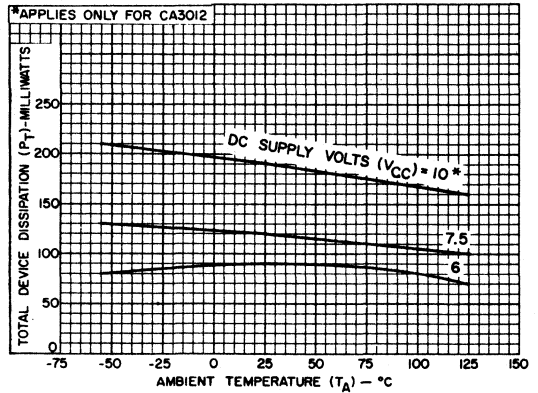


Fig. 4

VOLTAGE-GAIN TEST SETUP

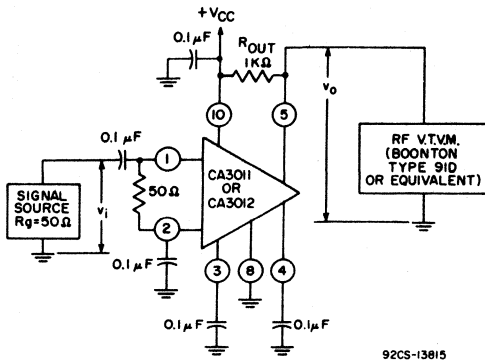


Fig. 5

PROCEDURES

A - Voltage Gain:

- 1) Set input frequency at desired value, $v_i = 100 \mu\text{V rms}$.
- 2) Record v_o .
- 3) Calculate Voltage Gain A from $A = 20 \log_{10} v_o/v_i$
- 4) Repeat Steps 1, 2, and 3 for each frequency and/or for temperature desired.

B - Input Limiting Voltage (Knee):

- 1) Repeat Steps A1 and A2, using $v_i = 100 \text{ mV}$
- 2) Decrease v_i to the level at which v_o is 3 dB below its value for $v_i = 100 \text{ mV}$.
- 3) Record v_i as Input Limiting Voltage (Knee).

VOLTAGE GAIN & INPUT LIMITING VOLTAGE VS TEMPERATURE

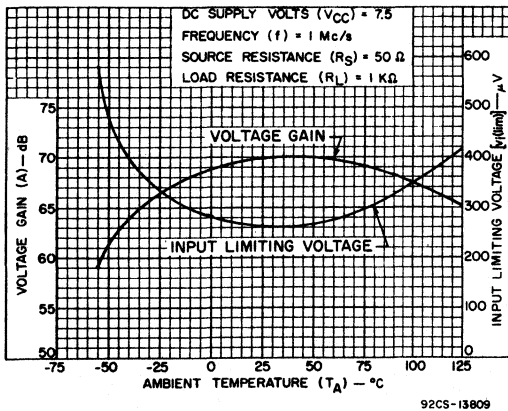


Fig. 6

VOLTAGE GAIN AND INPUT LIMITING VOLTAGE VS FREQUENCY

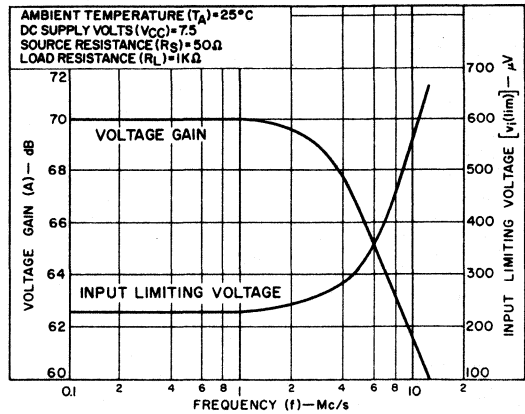


Fig. 7

TYPICAL CHARACTERISTICS AND TEST SETUPS

INPUT-IMPEDANCE COMPONENTS
TEST SETUP

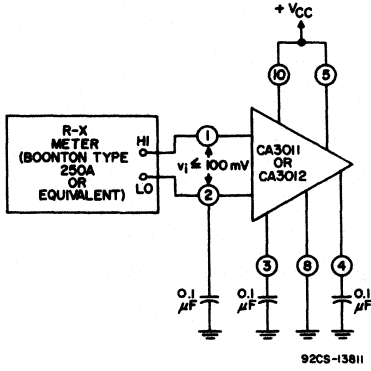


Fig. 8

INPUT-IMPEDANCE COMPONENTS
VS FREQUENCY

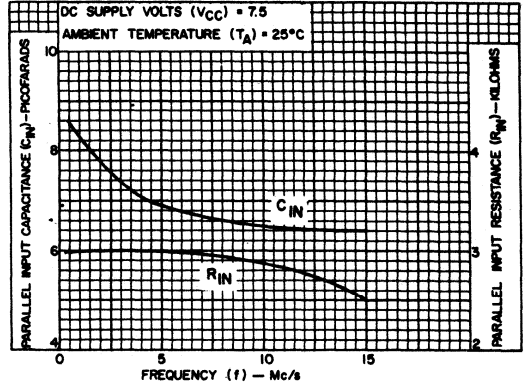


Fig. 9

OUTPUT-IMPEDANCE COMPONENTS
TEST SETUP

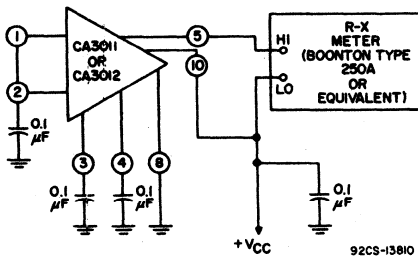


Fig. 10

OUTPUT-IMPEDANCE COMPONENTS
VS FREQUENCY

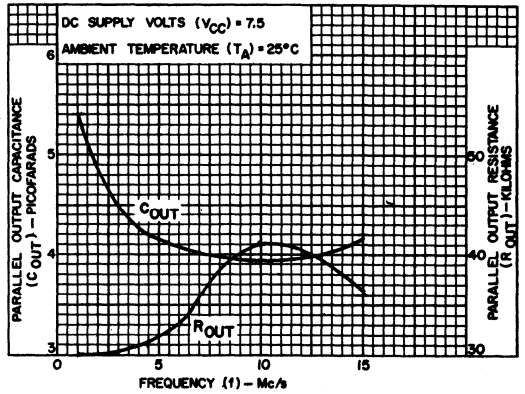


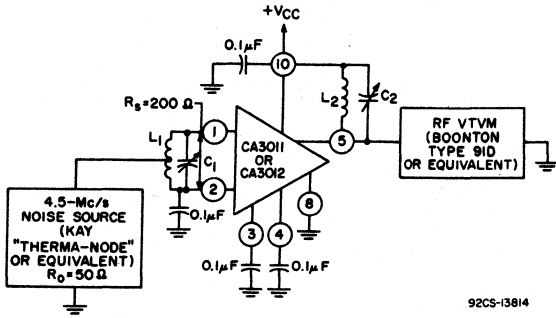
Fig. 11

Linear Integrated Circuits

CA3011, CA3012

TYPICAL CHARACTERISTICS AND TEST SETUPS

NOISE FIGURE TEST SETUP

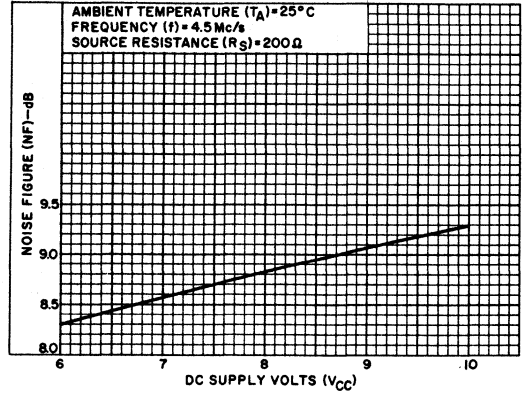


92CS-13814

- $L_1 = 82 \mu\text{H}$, center-tapped
- $L_2 = 2.36 \mu\text{H}$
- $C_1, C_2 = \text{Arco Type 423 padder, or equivalent}$

Fig. 12

NOISE FIGURE VS DC SUPPLY VOLTAGE



92CS-13788

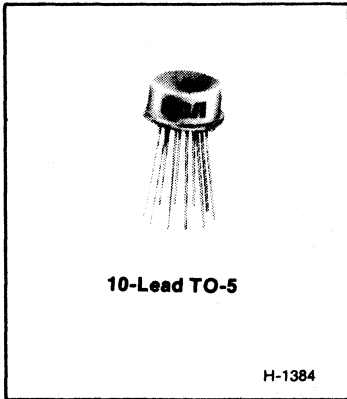
Fig. 13

Wide-Band Amplifier Discriminators

Features & Applications:

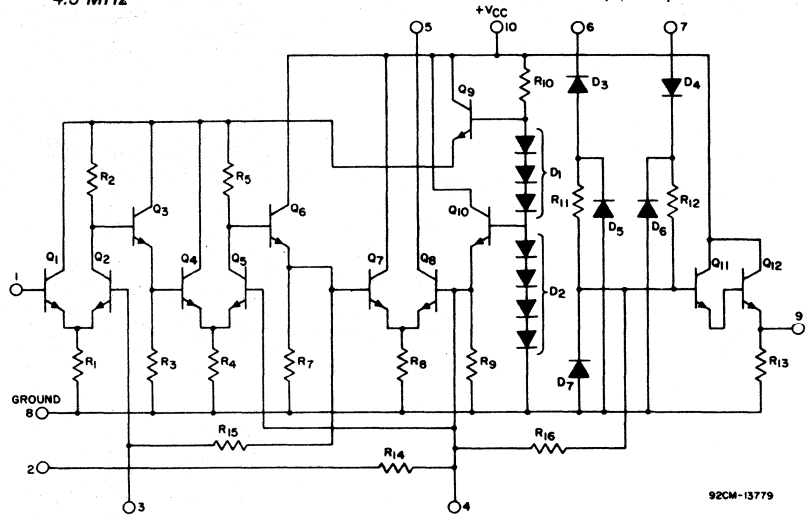
- Exceptionally high gain: power gain at 4.5 MHz - 75 dB typ.
- Excellent limiting characteristics - input limiting voltage (knee) = 300 μ V typ. at 4.5 MHz
- Excellent AM rejection: > 50 dB at 4.5 MHz

- High audio-voltage recovery - 220 mV typ at 4.5 MHz, 25 kHz deviation
- Wide frequency capability - 100 kHz to > 20 MHz
- Comprehensive circuit functions: if amplifier, AM and noise limiter, FM detector, audio preamplifier



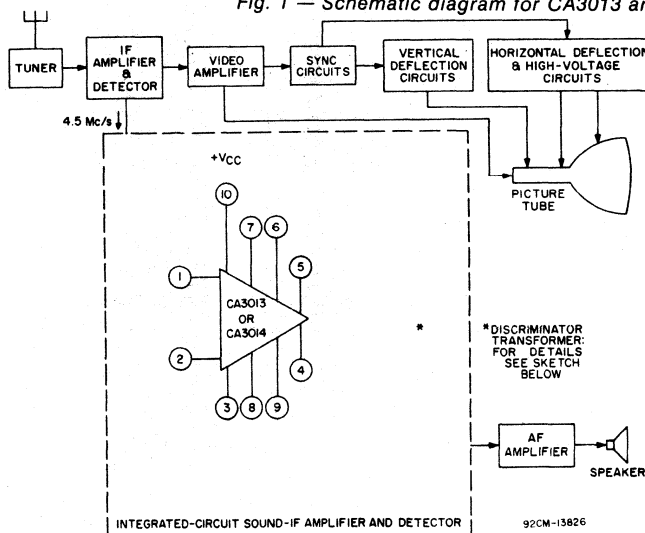
10-Lead TO-5

H-1384



92CM-13779

Fig. 1 - Schematic diagram for CA3013 and CA3014



92CM-13826

Fig. 2 - Block diagram of typical television receiver using RCA integrated-circuit sound-if amplifier and detector section

Linear Integrated Circuits

CA3013, CA3014

ABSOLUTE-MAXIMUM VOLTAGE LIMITS AT $T_A = 25^\circ C$

Indicated voltage limits for each terminal can be applied under the specified voltage conditions for other terminals. All voltages are with respect to ground (Terminal 8).

CA3013

TERMINAL	VOLTAGE LIMITS		VOLTAGE CONDITIONS AT OTHER TERMINALS									
			1	2	3	4	5	6	7	8	9	10
1	-3	+3	-	Same as 1	Do Not Apply External Voltage	+2.5 to +7.5	+7.5	Same as 4	Same as 4	Ground	AF Output	+7.5
2	-3	+3	Same as 2	-		+2.5 to +7.5	+7.5	Same as 4	Same as 4	Ground	AF Output	+7.5
3	-3	+3	-3 to +3	Same as 1		+2.5 to +7.5	+7.5	Same as 4	Same as 4	Ground	AF Output	+7.5
4	+2.5	+7.5	-3 to +3	Same as 1		-	+7.5	Same as 4	Same as 4	Ground	AF Output	+7.5
5	0	+10	-3 to +3	Same as 1		+2.5 to +7.5	-	Same as 4	Same as 4	Ground	AF Output	+7.5
6	+2.5	+7.5	-3 to +3	Same as 1		Same as 6	+7.5	-	Same as 4	Ground	AF Output	+7.5
7	+2.5	+7.5	-3 to +3	Same as 1		+2.5 to +7.5	+7.5	Same as 4	-	Ground	AF Output	+7.5
8	-3	+7.5	-3 to +3	Same as 1		+2.5 to +7.5	+7.5	Same as 4	Same as 4	Ground	AF Output	+7.5
9	0	+7.5	-3 to +3	Same as 1		+2.5 to +7.5	+7.5	Same as 4	Same as 4	Ground	-	+7.5
10	0	+10	-3 to +3	Same as 1		+2.5 to +7.5	+7.5	Same as 4	Same as 4	Ground	AF Output	-
CASE	INTERNALLY CONNECTED TO TERMINAL No.8 (GROUND TERMINAL)											

CA3014

TERMINAL	VOLTAGE LIMITS		VOLTAGE CONDITIONS AT OTHER TERMINALS									
			1	2	3	4	5	6	7	8	9	10
1	-3	+3	-	Same as 1	Do Not Apply External Voltage	+2.5 to +10	+10	Same as 4	Same as 4	Ground	AF Output	+10
2	-3	+3	Same as 2	-		+2.5 to +10	+10	Same as 4	Same as 4	Ground	AF Output	+10
3	-3	+3	-3 to +3	Same as 1		+2.5 to +10	+10	Same as 4	Same as 4	Ground	AF Output	+10
4	+2.5	+10	-3 to +3	Same as 1		-	+10	Same as 4	Same as 4	Ground	AF Output	+10
5	0	+13	-3 to +3	Same as 1		+2.5 to +10	-	Same as 4	Same as 4	Ground	AF Output	+10
6	+2.5	+10	-3 to +3	Same as 1		Same as 6	+10	-	Same as 4	Ground	AF Output	+10
7	+2.5	+10	-3 to +3	Same as 1		+2.5 to +10	+10	Same as 4	-	Ground	AF Output	+10
8	-3	+10	-3 to +3	Same as 1		+2.5 to +10	+10	Same as 4	Same as 4	Ground	AF Output	+10
9	0	+10	-3 to +3	Same as 1		+2.5 to +10	+10	Same as 4	Same as 4	Ground	-	+10
10	0	+13	-3 to +3	Same as 1		+2.5 to +10	+10	Same as 4	Same as 4	Ground	AF Output	-
CASE	INTERNALLY CONNECTED TO TERMINAL No.8 (GROUND TERMINAL)											

OPERATING-TEMPERATURE RANGE -55 to $+125^\circ C$

STORAGE-TEMPERATURE RANGE -65 to $+150^\circ C$

MAXIMUM INPUT-SIGNAL VOLTAGE:

Between Terminals 1 and 2 $\pm 3 V$

MAXIMUM DEVICE DISSIPATION 300 mW

RECOMMENDED MINIMUM DC

SUPPLY VOLTAGE (V_{CC}) 5.5 V

Example of use of LIMITS TABLE:

For RCA-CA3013, a maximum voltage of ± 3 volts may be applied to Terminal 1 under the following conditions:

Terminal 2 is at the same dc potential as Terminal 1

Terminal 3: do not apply external voltage

Terminal 4 is at any dc potential between +2.5 and +7.5 volts

Terminal 5 is at a dc potential of +7.5 volts

Terminals 6 and 7 are at the same dc potential as Terminal 4

Terminal 8 is at dc ground potential

Terminal 9 is used as the af output terminal

Terminal 10 is at a dc potential of +7.5 volts

TV/CATV Circuits
CA3013, CA3014

ELECTRICAL CHARACTERISTICS (See Page 8 for Definitions of Terms)	SYMBOLS	TEST CONDITIONS				LIMITS						TYPICAL CHARACTERISTICS CURVES Fig.	
		SETUP & PROCEDURE	FREQUENCY f	DC SUPPLY VOLTAGE V _{CC}	AMBIENT TEMPERATURE T _A	RCA CA3013			RCA CA3014				UNITS
						Min.	Typ.	Max.	Min.	Typ.	Max.		
Fig.	Mc/s	volts	°C	Min.	Typ.	Max.	Min.	Typ.	Max.				
Total Device Dissipation*	P _T	3	-	6	-55	-	80	-	73	80	120	mW	4
					+25	60	90	133	73	90	110	mW	
					+125	-	70	-	60	70	110	mW	
		3	-	7.5	-55	-	130	-	106	130	170	mW	4
					+25	87	120	187	106	120	150	mW	
					+125	-	100	-	90	100	150	mW	
		3	-	10	-55	-	-	-	165	210	250	mW	4
					+25	-	-	-	165	190	230	mW	
					+125	-	-	-	150	160	230	mW	
Voltage Gain**	A	5	1	6	-55	-	55	-	50	55	-	dB	6
					+25	60	66	-	60	66	-	dB	
					+125	-	61	-	50	61	-	dB	
		5	1	7.5	-55	-	59	-	55	59	-	dB	6
					+25	65	70	-	65	70	-	dB	
					+125	-	65	-	55	65	-	dB	
		5	1	10	-55	-	-	-	55	61	-	dB	6
					+25	-	-	-	65	71	-	dB	
					+125	-	-	-	55	66	-	dB	
		5	4.5	7.5	+25	60	67	-	60	67	-	dB	7
					+25	55	60	-	55	60	-	dB	
		Input-Impedance Components: Parallel Input Resistance	R _{IN}	8	4.5	7.5	+25	-	3	-	-	3	-
Parallel Input Capacitance	C _{IN}												
Output-Impedance Components: Parallel Output Resistance	R _{OUT}	10	4.5	7.5	+25	-	31.5	-	-	31.5	-	kΩ	11
Noise Figure	NF	12	4.5	7.5	+25	-	8.7	-	-	8.7	-	dB	13
Input Limiting Voltage (Knee)	v _{I(lim)}	14	4.5	7.5	+25	-	300	450	-	300	400	μV	15
Recovered AF Voltage	v _{O(af)}	14	4.5	6	+25	-	155	-	-	155	-	mV	15
				7.5	+25	128	188	-	135	188	-	mV	
				10	+25	-	-	-	-	220	-	mV	
Amplitude-Modulation Rejection	AMR	16	4.5	7.5	+25	-	50	-	-	50	-	dB	-
Discriminator Output Resistance	R _{O(disc)}	-	4.5	7.5	+25	-	60	-	-	60	-	Ω	-
Total Harmonic Distortion	THD	14	4.5	7.5	+25	-	1.8	-	-	1.8	-	%	17

* Total current drain may be determined by dividing P_T by V_{CC}.

** Recommended minimum dc supply voltage (V_{CC}) is 5.5 V.
Nominal load current flowing into terminal 5 is 1.5 mA at 7.5 V.

Linear Integrated Circuits

CA3013, CA3014

TYPICAL CHARACTERISTICS AND TEST SETUPS

DISSIPATION TEST SETUP

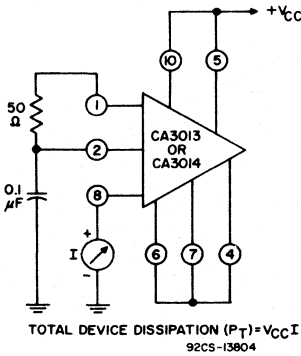


Fig.3

DISSIPATION vs. TEMPERATURE

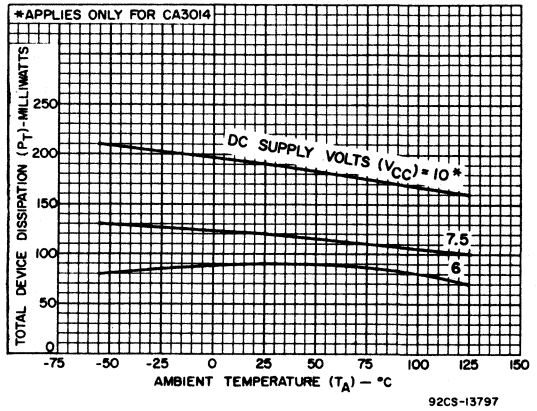
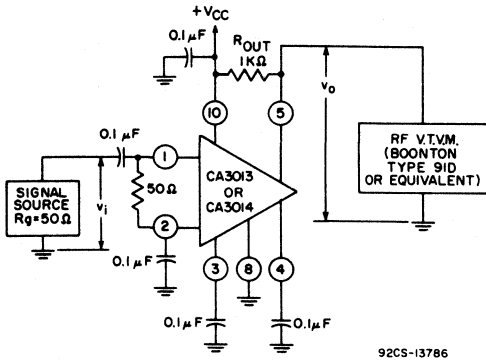


Fig.4

VOLTAGE-GAIN TEST SETUP



92CS-13786

PROCEDURE:

- 1) Set input frequency at desired value, $v_i = 100 \mu\text{V rms}$.
- 2) Record v_o .
- 3) Calculate Voltage Gain A from $A = 20 \log_{10} v_o/v_i$.
- 4) Repeat Steps 1, 2, and 3 for each frequency and/or temperature desired.

Fig.5

1-Mc/s VOLTAGE GAIN vs. TEMPERATURE

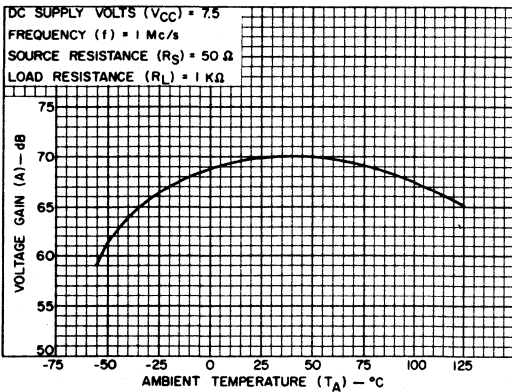


Fig.6

VOLTAGE GAIN vs. FREQUENCY

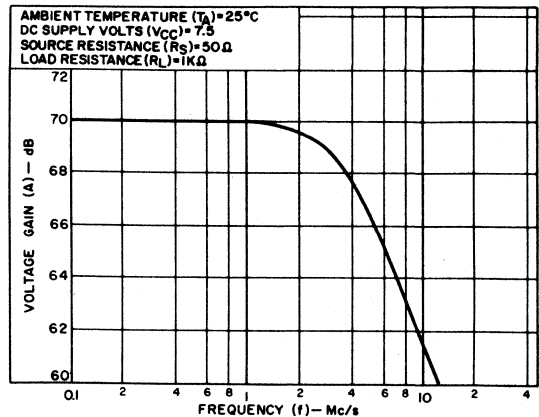


Fig.7

TYPICAL CHARACTERISTICS AND TEST SETUPS

INPUT-IMPEDANCE COMPONENTS TEST SETUP

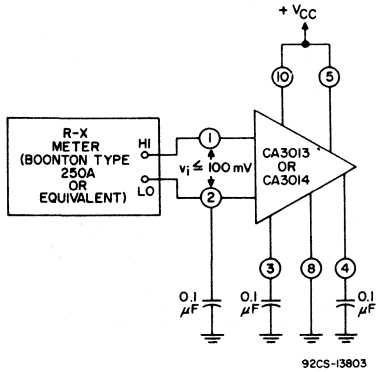


Fig. 8

INPUT-IMPEDANCE COMPONENTS vs. FREQUENCY

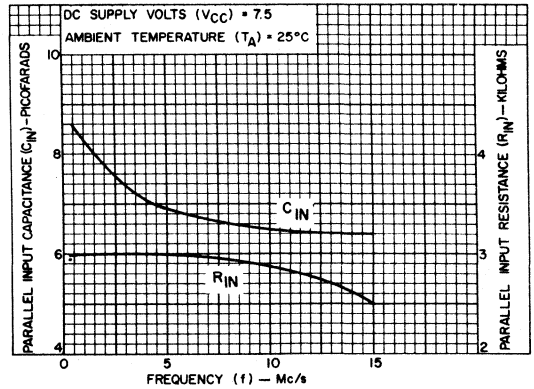


Fig. 9

OUTPUT-IMPEDANCE COMPONENTS TEST SETUP

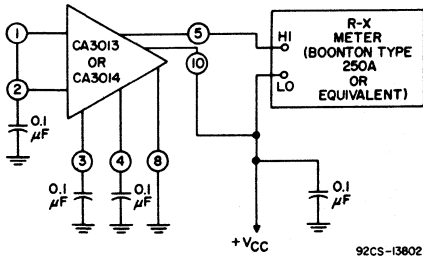


Fig. 10

OUTPUT-IMPEDANCE COMPONENTS vs. FREQUENCY

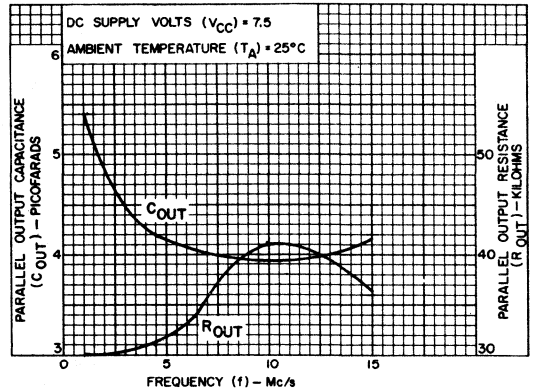
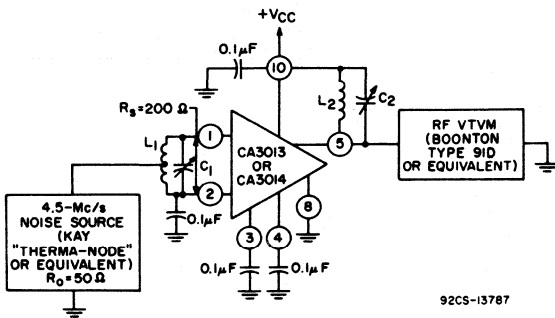


Fig. 11

NOISE FIGURE TEST SETUP



- $L_1 = 82 \mu\text{H}$, center-tapped
- $L_2 = 2.36 \mu\text{H}$
- $C_1, C_2 =$ Arco Type 423 padder, or equivalent

Fig. 12

NOISE FIGURE vs. DC SUPPLY VOLTAGE

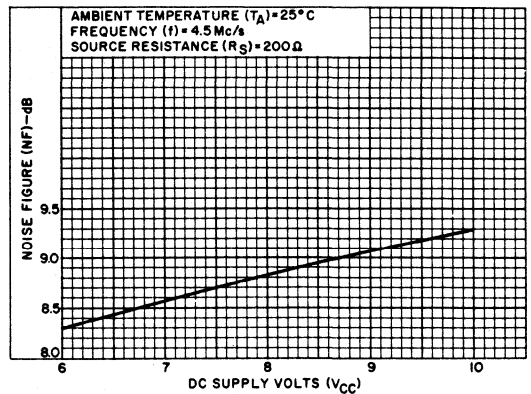
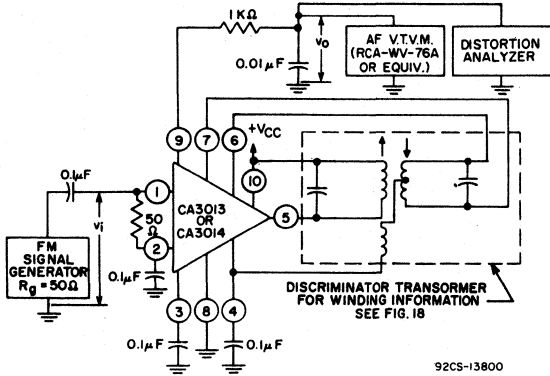


Fig. 13

CA3013, CA3014

TYPICAL CHARACTERISTICS AND TEST SETUPS

INPUT LIMITING VOLTAGE, RECOVERED AF VOLTAGE, AND TOTAL HARMONIC DISTORTION TEST SETUP



PROCEDURE:

A - Recovered-AF Voltage Output:

- 1) Set input frequency = 4.5 Mc/s, $v_i = 100$ mV rms, modulating frequency = 1 kc/s, frequency deviation = ± 25 kc/s.
- 2) Record v_o as Recovered-AF Voltage Output.

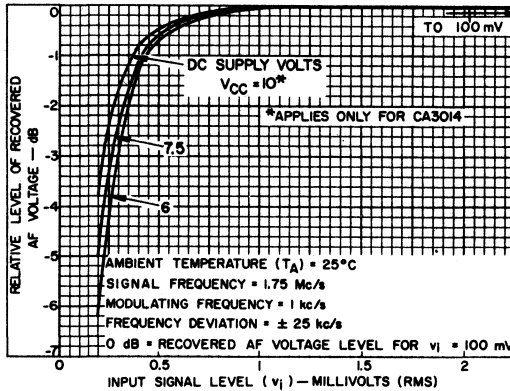
B - Input Limiting Voltage (Knee):

- 1) Repeat Steps A1 and A2, using $v_i = 100$ mV rms.
- 2) Decrease v_i to the level at which v_o is 3 dB below its value for $v_i = 100$ mV.
- 3) Record v_i as Input Limiting Voltage (Knee).

Fig. 14

INPUT LIMITING VOLTAGE (KNEE) AND RECOVERED AF VOLTAGE

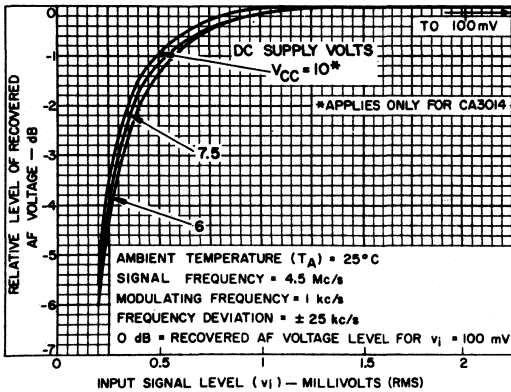
at 1.75 Mc/s



92CS-13793

(a)

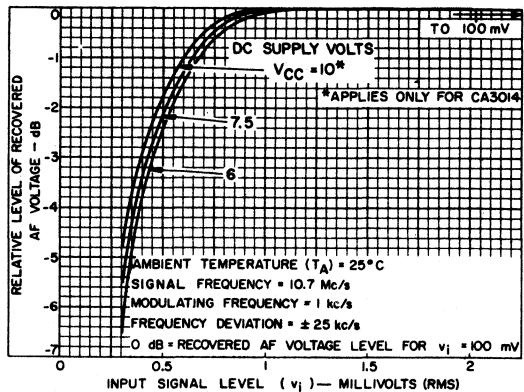
at 4.5 Mc/s



92CS-13792

(b)

at 10.7 Mc/s



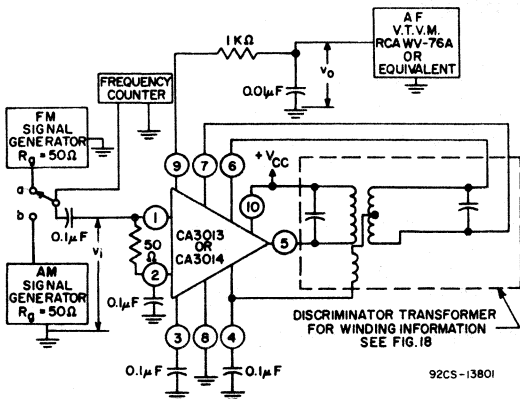
92CS-13791

(c)

Fig. 15

TYPICAL CHARACTERISTICS AND TEST SETUPS

AM-REJECTION TEST SETUP



PROCEDURE:

- 1) With Switch S in position "a", set input frequency = 4.5 Mc/s, $v_i = 10$ mV rms, modulating frequency = 1 kc/s, frequency deviation = ± 25 kc/s.
- 2) Record v_o .
- 3) Place Switch S in position "b", and set input frequency = 4.5 Mc/s, $v_i = 10$ mV rms, modulating frequency = 1 kc/s, % modulation = 50.
- 4) Measure v_o , and record value in dB below value in Step 2 as AM Rejection.

Fig. 16

TOTAL HARMONIC DISTORTION vs. DC SUPPLY VOLTAGE

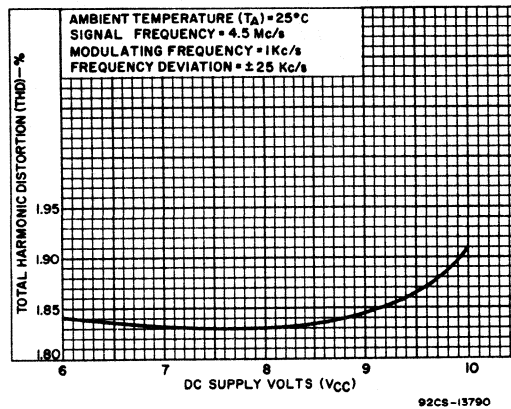
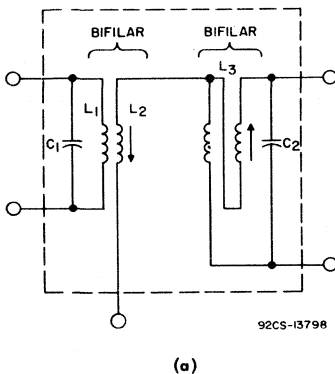


Fig. 17

DISCRIMINATOR TRANSFORMER SCHEMATIC



(a)

CONSTRUCTION DETAILS OF DISCRIMINATOR TRANSFORMERS SHOWN IN FIGS. 2, 14 AND 16

Coil-Form Outside Diameter = 7/32 inch

Slugs: Radio Industries, Inc. Type "E" Material, or equivalent

Wire Type: "GRIPPEZE"*, or equivalent

Operating Frequency Mc/s	Wire Size (AWG #)	Turns			C1 pF	C2 pF
		L1 [▲]	L2 [▲]	L3		
1.75	40	44	20	44 total (22 bifilar wound)	820	820
4.5	36	18	7	22 total (11 bifilar wound)	560	330
10.7	36	18	18	18 total (9 bifilar wound)	100	100

* Registered Trade Mark, Phelps-Dodge Copper Products.

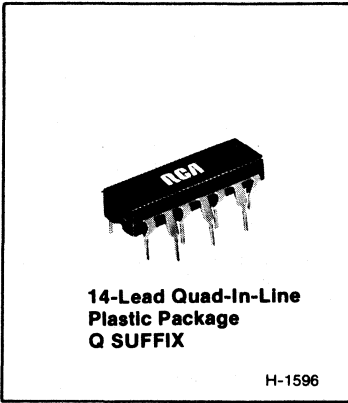
▲ wound bifilar.

NOTE: The mutual coupling between L1 and L3 is adjusted for the desired degree of linearity.

Fig. 18

(b)

CA3041



**Wide-Band Amplifier, FM Detector
AF Preamplifier/Driver**

Monolithic Silicon

For Sound Sections of TV Receivers Using
Tube-Type AF Output Amplifiers

Features:

- High-sensitivity - input limiting voltage (knee) = 150 μ V typ. at 4.5 MHz
- Large audio drive voltage capability
- Excellent AM rejection - 58 dB typ. at 4.5 MHz
- Inherent high stability - internally shielded
- Internal Zener-diode-regulated voltage supply
- Low harmonic radiation
- Wide frequency capability - <100 kHz to > 20 MHz
- Low harmonic distortion

RCA Integrated Circuit Type CA3041 provides, in a single monolithic silicon chip, a major subsystem for the sound sections of TV receivers. As shown in the Schematic Diagram (Fig. 1) and the TV Receiver Block Diagrams (Fig. 2) the CA3041 contains a multistage wide-band if-amplifier/limiter section, an FM-detector stage, a Zener-diode-regulated power-supply section, and an af-amplifier section specifically designed to drive directly a 6AQ5 beam power tube or other audio output tube of similar characteristics.

In FM receivers, the CA3041 can be used to provide if amplification and limiting, FM detection, and af pre-amplification.

The CA3041 provides exceptional versatility of circuit design because the if-amplifier/limiter section, FM detector section, and af-preamplifier/driver section can be used independently of each other.

The CA3041 utilizes a 14-lead dual-in-line plastic package with leads specially formed to facilitate automatic insertion of the device in suitably punched printed-circuit boards. Templates showing recommended layout of printed-circuit boards for the CA3041 are provided in this bulletin (Figs. 13, 14 and 15).

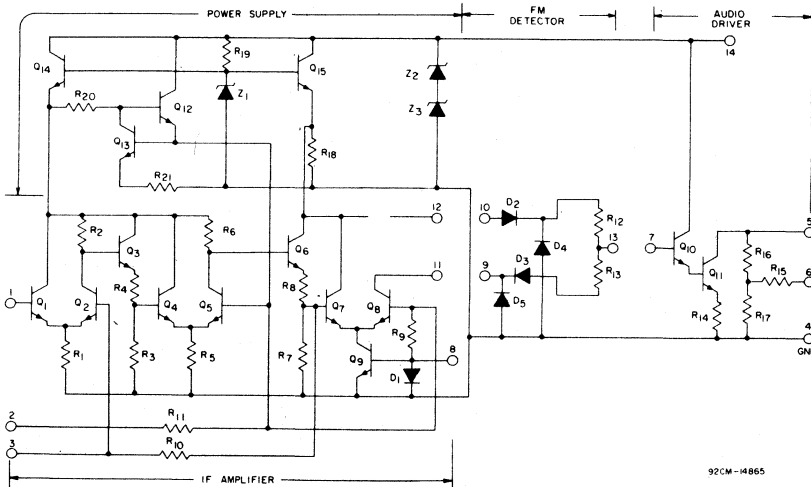


Fig. 1 — Schematic diagram.

ABSOLUTE-MAXIMUM VOLTAGE AND CURRENT LIMITS AT $T_A = 25^\circ\text{C}$

Indicated voltage or current limits for each terminal may be applied under the specified voltage conditions for other terminals. All voltages are with respect to ground (Terminal 4).

TERMINAL	VOLTAGE OR CURRENT LIMITS		VOLTAGE CONDITIONS AT OTHER TERMINALS													
			1	2	3	4	5	6	7	8	9	10	11	12	13	14
1	-3 V	+3 V	-	AT SAME DC VOLTAGE AS TERMINAL 1	EXTERNAL DC VOLTAGE IS NOT NORMALLY APPLIED TO THIS TERMINAL	GROUND (VOLTAGE REFERENCE TERMINAL)	CONNECTED TO +140 V THROUGH 47 k Ω RESISTOR*	CONNECTED TO TERMINAL 7 THROUGH 100 k Ω RESISTOR*	AF-INPUT TERMINAL (EXTERNAL DC VOLTAGE IS NOT NORMALLY APPLIED TO THIS TERMINAL)	DC VOLTAGE IS NOT NORMALLY APPLIED TO THIS TERMINAL	AT SAME DC VOLTAGE AS TERMINAL 12 (EXCEPT TERMINAL 9)	AT SAME DC VOLTAGE AS TERMINAL 12 (EXCEPT TERMINAL 10)	AT SAME DC VOLTAGE AS TERMINAL 12 (EXCEPT TERMINAL 11)	EXTERNAL DC VOLTAGE IS NOT NORMALLY APPLIED TO THIS TERMINAL	AT SAME DC VOLTAGE AT TERMINAL 12 (EXCEPT TERMINAL 13)	CONNECTED TO +140 V DC THROUGH 6.2-k Ω RESISTOR*
2	-3 V	+3 V	-3 to +3													
3	-3 V	+3 V	-3 to +3													
4	GROUND (VOLTAGE REFERENCE TERMINAL)		-3 to +3													
5	20 mA		-3 to +3													
6	0 V	+10 V	-3 to +3													
7	10 mA		-3 to +3													
8	10 mA		-3 to +3													
9	10 mA		-3 to +3													
10	10 mA		-3 to +3													
11	+2.5 V	+5 V	-3 to +3													
12	+2.5 V	+5 V	-3 to +3													
13	+2.5 V	+5 V	-3 to +3													
14	50 mA		-3 to +3													

* Any other combination of DC Supply Voltage and Series Resistance which will not cause the Maximum Device Dissipation Limit or any of the Maximum Voltage or Current Limits for the CA3041 to be exceeded may be used.

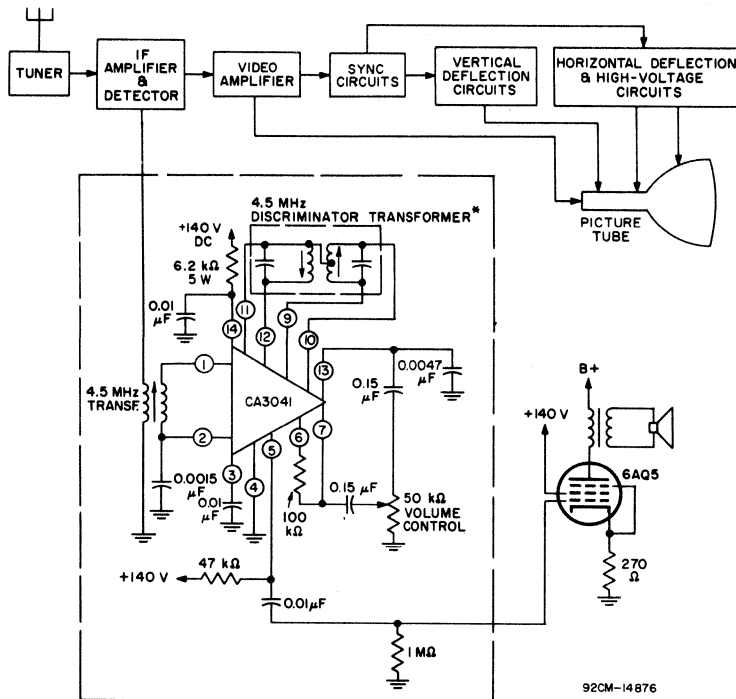
OPERATING-TEMPERATURE RANGE 0° to $+85^\circ\text{C}$
 STORAGE-TEMPERATURE RANGE -25° to $+85^\circ\text{C}$
 MAXIMUM INPUT-SIGNAL VOLTAGE:
 Between Terminals 1 and 3 ± 3 V
 MAXIMUM DEVICE DISSIPATION:
 At Ambient } up to $+25^\circ\text{C}$ 950 mW
 Temperatures } above $+25^\circ\text{C}$ derate at 10.8 mW/ $^\circ\text{C}$

Linear Integrated Circuits

CA3041

ELECTRICAL CHARACTERISTICS, at an Ambient Temperature, T_A , of 25°C , and a DC Supply Voltage, V_{CC} , of +140 Volts applied to Terminal 14 through a resistance of $6.2\text{ k}\Omega$, unless otherwise indicated. Any other combination of DC Supply Voltage and Series Resistance which will not cause the Maximum Dissipation Limit or any of the Maximum Voltage or Current Limits for the CA3041 to be exceeded may be used.

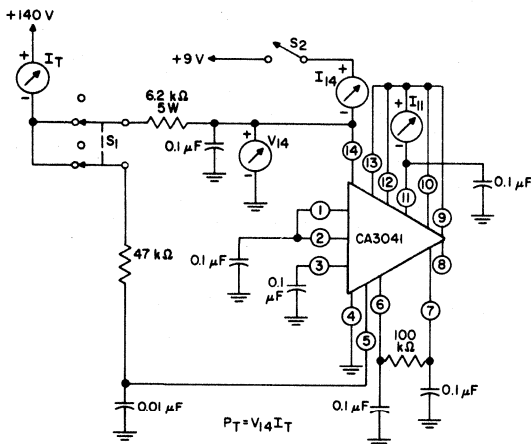
CHARACTERISTICS (See Page 7 for Definitions of Terms)	SYMBOLS	TEST CONDITIONS		LIMITS			TYPICAL CHARACTERISTICS CURVES	
		SETUP AND PROCEDURE	SPECIAL CONDITIONS	TYPE CA3041				
				Fig.	Min.	Typ.		Max.
Total Device Dissipation	P_T	3	$T_A = \begin{matrix} 0^\circ\text{C} \\ +25^\circ\text{C} \\ +85^\circ\text{C} \end{matrix}$	220 225 230	245 250 255	270 275 280	mW mW mW	4
Zener Regulating Voltage (DC Supply Voltage at Terminal 14)	V_{14}	-		10.5	11.2	12.1	V	-
Quiescent Operating Current (into Terminal 11)	I_{11}	3		0.25	0.63	1	mA	-
9-Volt Current Drain (Quiescent Operating Current into Terminal 14)	I_{14}	3	$V_{CC} = +9\text{ V}$ applied directly to Terminal 14	7	11	16	mA	-
Input-Impedance Components: Parallel Input Resistance	R_i	5	$f = 4.5\text{ MHz}$	-	11	-	$\text{k}\Omega$	-
Parallel Input Capacitance	C_i	5		-	5	-	pF	-
Output-Impedance Components: Parallel Output Resistance	R_o	-		-	100	-	$\text{k}\Omega$	-
Parallel Output Capacitance	C_o	-		-	4	-	pF	-
Input Limiting Voltage (Knee)	$V_{i(lim)}$	6		-	150	200	$\mu\text{V (rms)}$	10
Amplitude-Modulation Rejection	AMR	7		45	58	-	dB	8
IF-Amplifier Voltage Gain	$A_{(IF)}$	9	-	67	-	dB	10	
Recovered AF Voltage: 1. At FM-Detector Output	$V_{o(af)}$	-	$R_L = 50\text{ k}\Omega, \Delta f = \pm 25\text{ kHz}$ THD = 0.7% (typ.)	-	250	-	mV (rms)	-
2. At AF-Driver Output in Test Setup		-	THD < 5%	8	9	-	V (rms)	-
Total Harmonic Distortion	THD	6	$V_{o(af)} = 8\text{ V (rms)}$	-	1.5	5	%	-
Discriminator Output Resistance	$R_{o(dis)}$	-	$f = 1\text{ kHz}$	-	10	-	$\text{k}\Omega$	-
AF-Amplifier Input Resistance	$R_{i(af)}$	-		-	100	-	$\text{k}\Omega$	-
AF-Amplifier Output Resistance	$R_{o(af)}$	-		-	30	-	$\text{k}\Omega$	-
AF-Driver Voltage Gain	A_{af}	11		-	41	-	dB	12



92CM-14876

* TRW Electronics, Des Plaines, Illinois. Part No. EQ23874, or equivalent.

Fig. 2 - Block diagram of typical TV receiver using CA3041.



92CS-14881

Fig. 3 - Test setup for total dissipation, quiescent operating current into terminal No. 11, and 9-volt current drain.

PROCEDURES:

Total Device Dissipation:

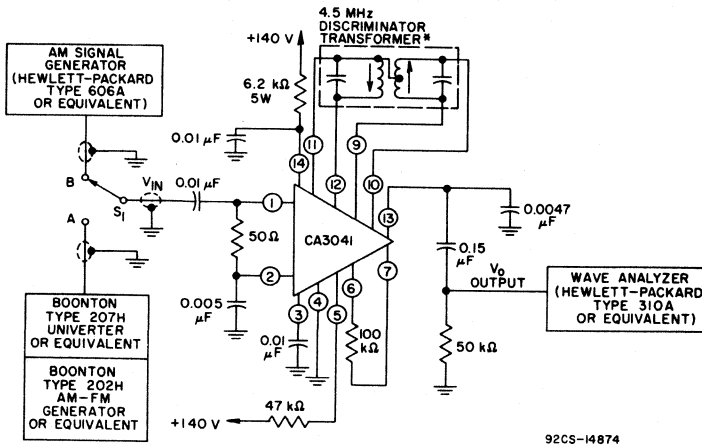
1. Close S₁, open S₂.
2. Measure and record V₁₄ and I_T.
3. Determine Total Device Dissipation from $P_T = V_{14} I_T$.

Quiescent Operating Current into Terminal 11:

1. Close S₁, open S₂.
2. Measure I₁₁ and record as Quiescent Operating Current into Terminal 11.

9-Volt Current Drain:

1. Open S₁, close S₂.
2. Measure I₁₄ and record as 9-Volt Current Drain.



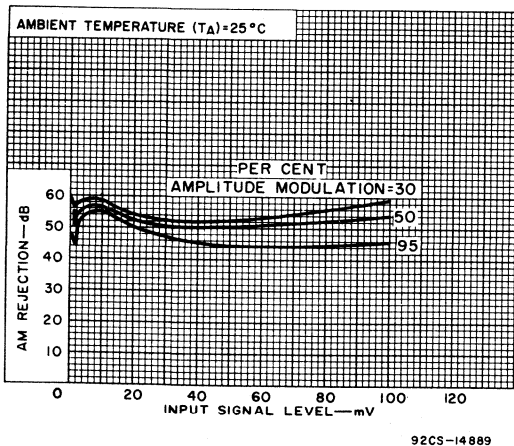
PROCEDURES:

1. Set FM Signal Generator as follows:
 Output frequency = 4.5 MHz
 Modulating frequency = 1000 Hz
 Deviation = ± 25 kHz
 Output level for V_{in} = 100 mV rms
2. Set AM Signal Generator as follows:
 Output frequency = 4.5 MHz
 Modulating frequency = 1000 Hz
 Per cent modulation = 30
 Output level for V_{in} = 10 mV rms
3. With S_1 in Position A measure AF Output Voltage and record as $V_o(FM)$.
4. With S_1 in Position B measure AF Output Voltage and record as $V_o(AM)$.
5. Determine AM Rejection from $AMR = V_o(FM)/V_o(AM)$

92CS-14874

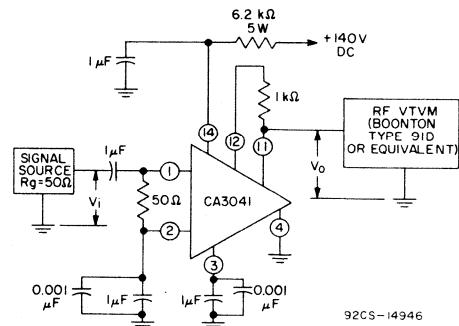
* TRW Electronics, Des Plaines, Illinois. Part No. E023874, or equivalent.

Fig. 7 - Test setup for measurement of AM rejection.



92CS-14889

Fig. 8 - Typical AM rejection characteristics for CA3041.



92CS-14946

PROCEDURE:

A - Voltage Gain:

- 1) Set input frequency at desired value, $v_i = 100 \mu V$ rms.
- 2) Record v_o .
- 3) Calculate Voltage Gain A from $A = 20 \log_{10} v_o/v_i$
- 4) Repeat Steps 1, 2, and 3 for each frequency and/or for temperature desired.

Fig. 9 - Test setup for measurement of IF-amplifier voltage gain.

Linear Integrated Circuits

CA3041

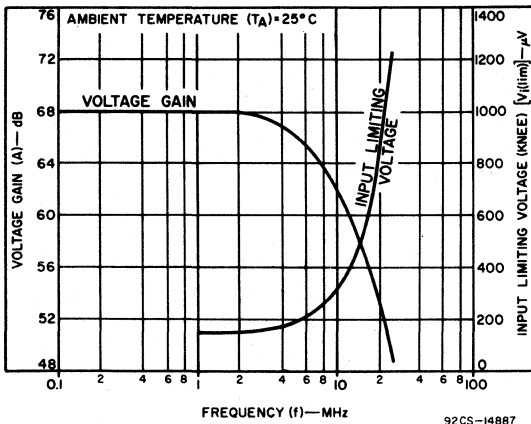


Fig.10 - Typical IF-amplifier voltage gain and input-limiting voltage (knee) characteristics.

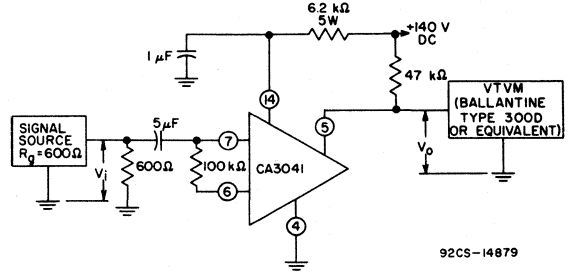


Fig.11 - Test setup for measurement of AF-amplifier voltage gain.

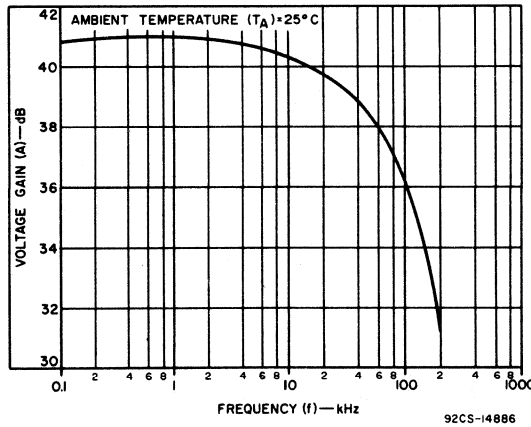


Fig.12 - Typical AF-driver voltage-gain characteristic.

DEFINITIONS OF TERMS

Total Device Dissipation (P_T)

The total power drain of the device with no signal applied and no external load current.

Voltage Gain (A)

The ratio of the signal voltage developed at the output of the device to the signal voltage applied to the input, expressed in dB.

Input Impedance

The ratio of a change in input voltage to a change in input current, measured at the input terminal of the device, with respect to ground.

Output Impedance

The ratio of a change in output voltage to a change in output current, measured at the output terminal of the device, with respect to ground.

Input Limiting Voltage (Knee) [$v_i(\text{lim})$]

The input signal voltage which will cause the output signal to decrease 3 dB from its maximum level.

Recovered AF Voltage [$v_o(\text{af})$]

The rms value of the AF output voltage of the device produced by a specified frequency deviation of an FM input signal.

Amplitude-Modulation Rejection (AMR)

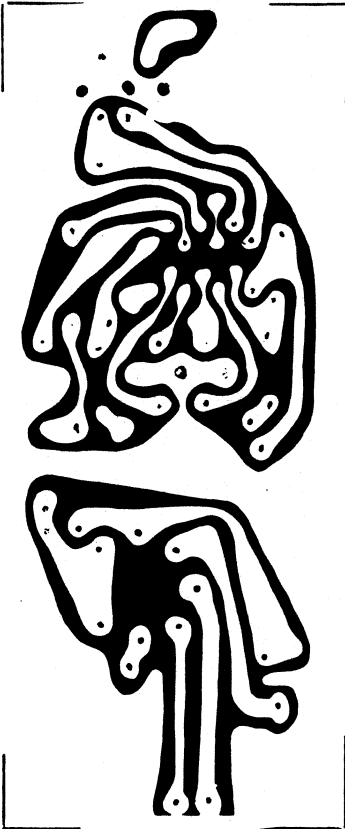
The ratio of the recovered AF output voltage produced by a specified frequency deviation of an FM input signal to the recovered AF output voltage produced by an amplitude-modulated input signal having the same carrier frequency, expressed in dB.

Discriminator Output Resistance [$R_O(\text{disc})$]

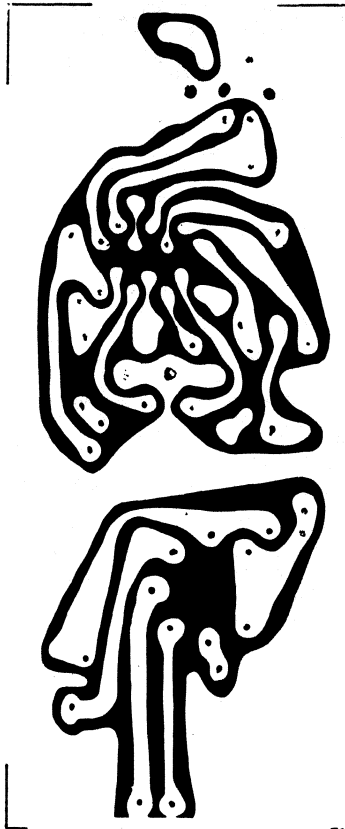
The ratio of a change in AF output voltage to a change in output current, measured between the output terminal of the device and ground.

Total Harmonic Distortion (THD)

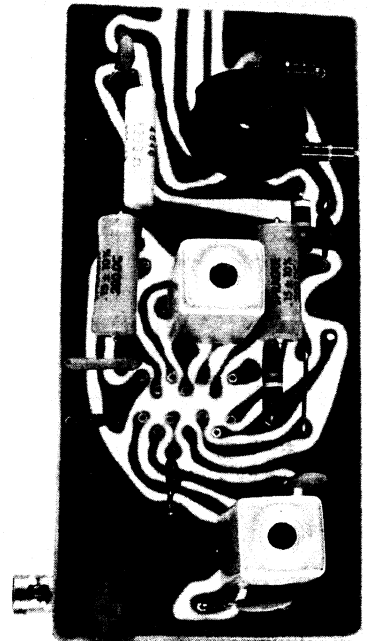
The ratio of the total rms voltage of all harmonics to the rms voltage of the fundamental, expressed in per cent. These voltages are measured at the af output terminal of the device, with respect to ground.



*Fig. 13 - Recommended layout of printed-circuit board for complete TV-receiver sound strip utilizing RCA-CA3041 (Top View).
(Actual Size)*

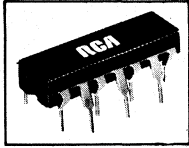


*Fig. 14 - Recommended layout of printed-circuit board for complete TV-receiver sound strip utilizing RCA-CA3041 (Bottom View).
(Actual Size)*



*Fig. 15 - Recommended parts layout for TV-receiver sound strip utilizing RCA-CA3041.
(Top View)*

CA3042



14-Lead Quad-In-Line Plastic Package
Q SUFFIX

H-1596

Wide-Band Amplifier, FM Detector AF Preamplifier/Driver

For Sound Sections of TV Receivers Using Transistor-Type AF Output Amplifiers

Features:

- High sensitivity - input limiting voltage (knee) = 150 μ V typ. at 4.5 MHz
- 6-mA audio drive capability
- Excellent AM rejection - 58 dB typ. at 4.5 MHz
- Inherent high stability - internally shielded
- Internal Zener-diode-regulated voltage supply
- Low harmonic radiation
- Wide frequency capability - <100 kHz to >20 MHz
- Low harmonic distortion

RCA Integrated Circuit Type CA3042 provides, in a single monolithic silicon chip, a major sub-system for the sound sections of TV receivers. As shown in the Schematic Diagram (Fig. 1) and the TV Receiver Block Diagrams (Figs. 2A and 2B) the CA3042 contains a multistage wide-band IF-amplifier section, an FM-detector stage, a Zener-diode-regulated power-supply section, and an AF-amplifier section specifically designed to drive directly an n-p-n audio output transistor or a high-gain audio output pentode tube.

In FM receivers, the CA3042 can be used to provide if amplification and limiting, FM detection, and af preamplification.

The CA3042 provides exceptional versatility of circuit design because the if-amplifier/limiter section, FM detector section, and af-preamplifier/driver section can be used independently of each other.

The CA3042 utilizes a 14-lead dual-in-line plastic package with leads specially formed to facilitate automatic insertion of the device in suitably punched printed-circuit boards. Templates showing recommended layout of printed-circuit boards for the CA3042 are provided in this bulletin (Figs. 13 & 14).

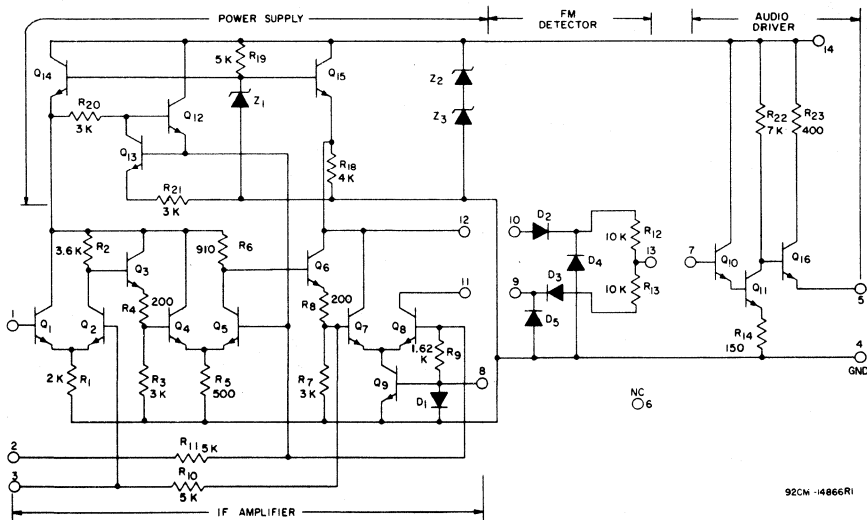


Fig. 1 — Schematic diagram.

92CM-4866R1

ABSOLUTE-MAXIMUM VOLTAGE AND CURRENT LIMITS AT $T_A = 25^\circ\text{C}$

Indicated voltage or current limits for each terminal may be applied under the specified voltage conditions for other terminals. All voltages are with respect to ground (Terminal 4).

TERMINAL	VOLTAGE OR CURRENT LIMITS		VOLTAGE CONDITIONS AT OTHER TERMINALS													
			1	2	3	4	5	6	7	8	9	10	11	12	13	14
1	-3 V	+3 V	-	AT SAME DC VOLTAGE AS TERMINAL 1	EXTERNAL DC VOLTAGE IS NOT NORMALLY APPLIED TO THIS TERMINAL	GROUND (VOLTAGE REFERENCE TERMINAL)	AF-DRIVER OUTPUT TERMINAL (EXTERNAL DC VOLTAGE IS NOT NORMALLY APPLIED TO THIS TERMINAL)	NO CONNECTION	AF-INPUT TERMINAL (EXTERNAL DC VOLTAGE IS NOT NORMALLY APPLIED TO THIS TERMINAL)	MUTING TERMINAL (EXTERNAL DC VOLTAGE IS NOT NORMALLY APPLIED TO THIS TERMINAL EXCEPT THAT TERMINAL MAY BE GROUNDED TO OBTAIN MUTING ACTION)	AT SAME DC VOLTAGE AS TERMINAL 12 (EXCEPT TERMINAL 9)	AT SAME DC VOLTAGE AS TERMINAL 12 (EXCEPT TERMINAL 10)	AT SAME DC VOLTAGE AS TERMINAL 12 (EXCEPT TERMINAL 11)	EXTERNAL DC VOLTAGE IS NOT NORMALLY APPLIED TO THIS TERMINAL	AT SAME DC VOLTAGE AT TERMINAL 12 (EXCEPT TERMINAL 13)	CONNECTED TO +140 V DC THROUGH 6.2-k Ω RESISTOR*
2	-3 V	+3 V	-3 to +3													
3	-3 V	+3 V	-3 to +3													
4	GROUND (VOLTAGE REFERENCE TERMINAL)		-3 to +3													
5	20 mA		-3 to +3													
6	NO CONNECTION		-3 to +3													
7	10 mA		-3 to +3													
8	10 mA		-3 to +3													
9	10 mA		-3 to +3													
10	10 mA		-3 to +3													
11	+2 V	+10 V	-3 to +3													
12	+2.5 V	+10 V	-3 to +3													
13	0 V	+10 V	-3 to +3													
14	50 mA		-3 to +3													

* Any other combination of DC Supply Voltage and Series Resistance which will not cause the Maximum Device Dissipation Limit or any of the Maximum Voltage or Current Limits for the CA3042 to be exceeded may be used.

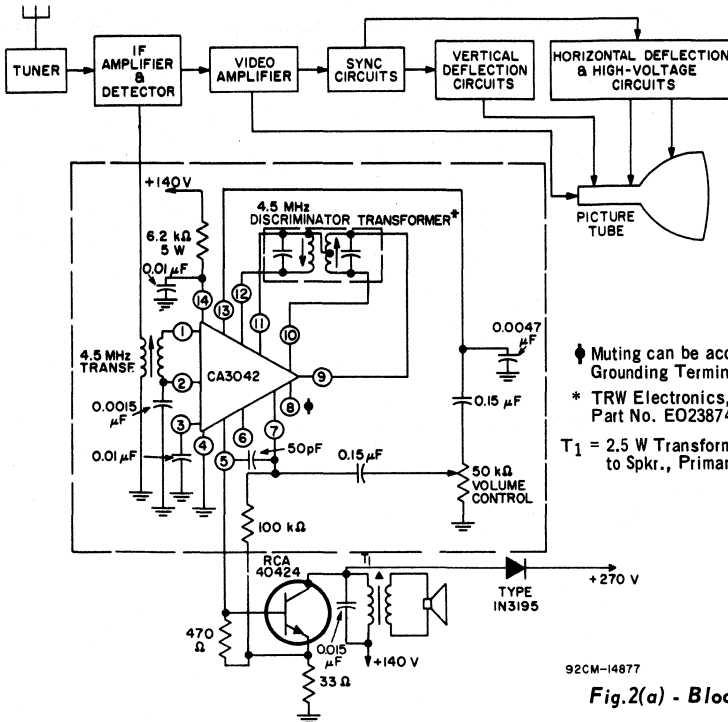
OPERATING-TEMPERATURE RANGE 0° to $+85^\circ\text{C}$
 STORAGE-TEMPERATURE RANGE -25° to $+85^\circ\text{C}$
 MAXIMUM INPUT-SIGNAL VOLTAGE:
 Between Terminals 1 and 3 ± 3 V
 MAXIMUM DEVICE DISSIPATION:
 At Ambient } up to $+25^\circ\text{C}$ 950 mW
 Temperatures } above $+25^\circ\text{C}$ derate at 10.8 mW/ $^\circ\text{C}$

Linear Integrated Circuits

CA3042

ELECTRICAL CHARACTERISTICS, at an Ambient Temperature, T_A , of 25°C , and a DC Supply Voltage, V_{CC} , of +140 Volts applied to Terminal 14 through a resistance of $6.2\text{ k}\Omega$, unless otherwise indicated. Any other combination of DC Supply Voltage and Series Resistance which will not cause the Maximum Dissipation Limit or any of the Maximum Voltage or Current Limits for the CA3042 to be exceeded may be used.

CHARACTERISTICS (See Page 7 for Definitions of Terms)	SYMBOLS	TEST CONDITIONS		LIMITS			TYPICAL CHARACTERISTICS CURVES Fig.		
		SETUP AND PROCEDURE Fig.	SPECIAL CONDITIONS	TYPE CA3042					
				Min.	Typ.	Max.		Units	
Total Device Dissipation	P_T	3	$T_A = \begin{matrix} 0^{\circ}\text{C} \\ +25^{\circ}\text{C} \\ +85^{\circ}\text{C} \end{matrix}$	200 210 220	230 240 250	260 270 280	mW mW mW	4	
Zener Regulating Voltage (DC Supply Voltage at Terminal 14)	V_{14}	—		10.5	11.2	12.1	V	—	
Quiescent Operating Current (into Terminal 11)	I_{11}	3		0.25	0.63	1	mA	—	
9-Volt Current Drain (Quiescent Operating Current into Terminal 14)	I_{14}	3	$V_{CC} = +9\text{ V}$ applied directly to Terminal 14	8	12	18	mA	—	
Input-Impedance Components: Parallel Input Resistance	R_i	5	$f = 4.5\text{ MHz}$ $\Delta f = \pm 25\text{ kHz}$	—	11	—	$\text{k}\Omega$	—	
Parallel Input Capacitance	C_i	5		—	5	—	pF	—	
Output-Impedance Components: Parallel Output Resistance	R_o	—		—	100	—	$\text{k}\Omega$	—	
Parallel Output Capacitance	C_o	—		—	4	—	pF	—	
Input Limiting Voltage (Knee)	$V_{i(\text{lim})}$	12		—	150	200	μV (rms)	9	
Amplitude-Modulation Rejection	AMR	6		45	58	—	dB	7	
IF-Amplifier Voltage Gain	$A(\text{IF})$	8		—	67	—	dB	9	
Recovered AF Voltage:	$V_o(\text{af})$								
1. At FM-Detector Output		12		$R_L = 50\text{ k}\Omega$ THD = 0.7% (typ.)	—	250	—	mV (rms)	—
2. At AF-Driver Output in Test Setup		12		$R_L = 322\ \Omega$ THD < 5%	500	800	—	mV (rms)	—
3. At AF-Driver Output in TV-Receiver Sound System		2A or 2B	$R_L = 150\text{ k}\Omega$ THD = 1.5% (typ.)	—	3	—	V (rms)	—	
Total Harmonic Distortion:	THD								
1. In Test Setup		12	$V_o(\text{af}) = 500\text{ mV}$ (rms)	—	1.5	5	%	—	
2. In TV Receiver Sound System		2A or 2B	$V_o(\text{af}) = 1.3\text{ V}$ (rms)	—	1	—	%	—	
FM-Detector Output Resistance	$R_o(\text{det})$	—	$f = 1\text{ kHz}$	—	10	—	$\text{k}\Omega$	—	
AF-Driver Input Resistance	$R_i(\text{af})$	—		—	100	—	$\text{k}\Omega$	—	
AF-Driver Output Resistance	$R_o(\text{af})$	—		—	250	—	Ω	—	
AF-Driver Voltage Gain	A_{af}	10		$R_S = 50\ \Omega, C_1 = 0$	—	30	—	dB	11



♦ Muting can be accomplished by Grounding Terminal No.8
 * TRW Electronics, Des Plaines, Illinois. Part No. EO23874, or equivalent.
 $T_1 = 2.5 \text{ W Transformer, Impedance, } 3500 \Omega \text{ to Spkr., Primary DC} = 40 \text{ mA}$

Fig.2(a) - Block diagram of typical TV receiver utilizing transistor RCA-40424.

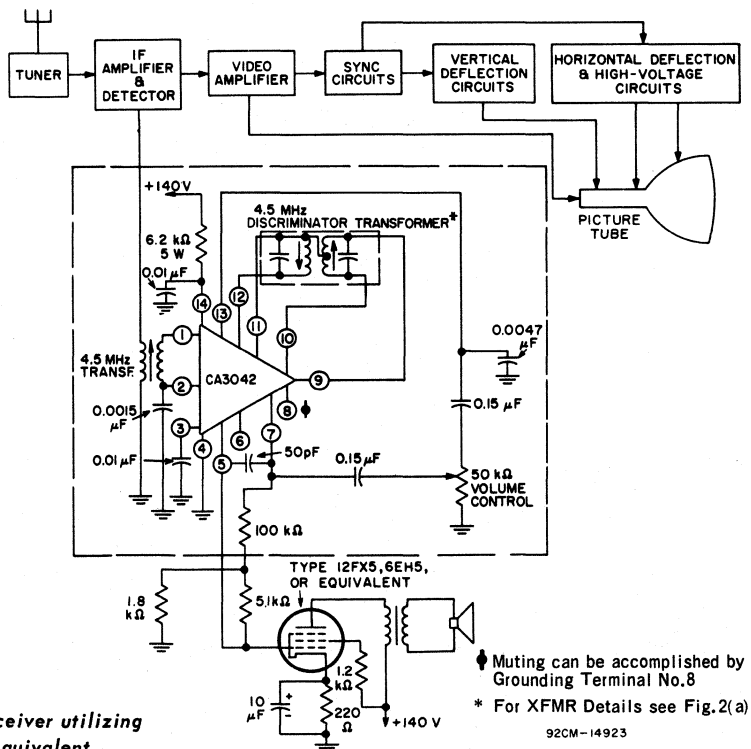
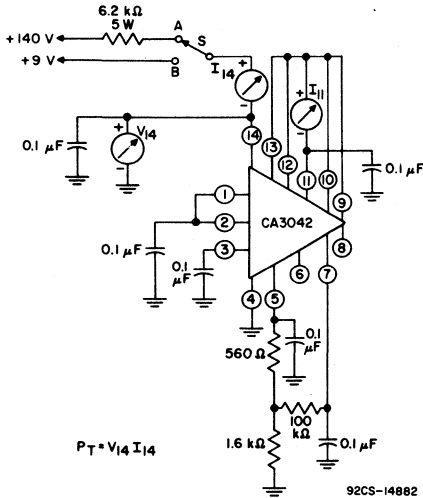


Fig.2(b) - Block diagram of typical TV receiver utilizing the CA3042 and a 12FX5, 6EH5, or equivalent.

CA3042



92CS-14882

PROCEDURES:

Total Device Dissipation:

1. Set switch S in position A
2. Measure and record V_{14} and I_{14} .
3. Determine Total Device Dissipation from $P_T = V_{14} I_{14}$

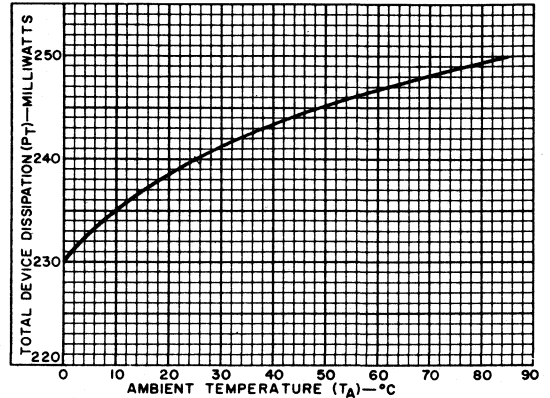
Quiescent Operating Current into Terminal 11:

1. Turn switch S to position B
2. Measure I_{11} and record as Quiescent Operating Current into Terminal 11.

9-Volt Current Drain:

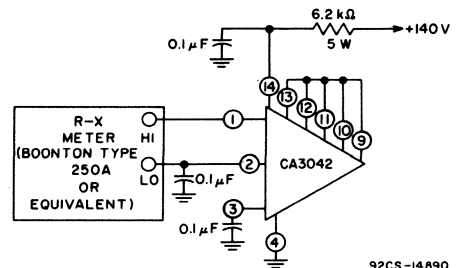
1. Set switch S in position B
2. Measure I_{14} and record as 9-Volt Current Drain.

Fig. 3 - Test setup for measurement of total device dissipation, quiescent current into terminal No. 11, and 9-volt current drain.



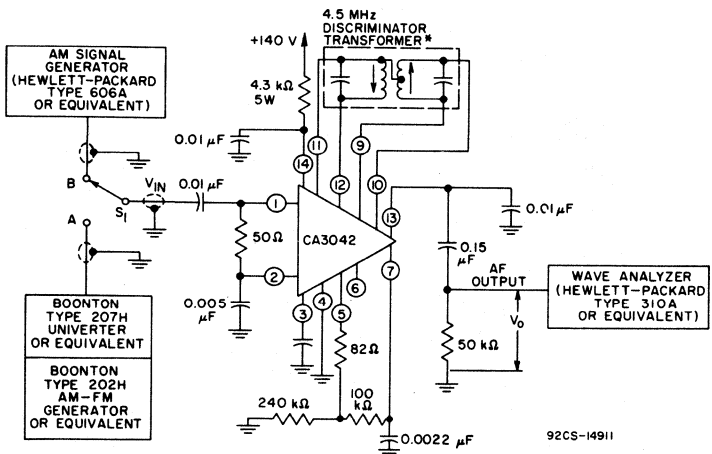
92CS-14888

Fig. 4 - Typical dissipation characteristic.



92CS-14890

Fig. 5 - Test setup for measurement of input-impedance components.



92CS-14911

Fig. 6 - Test setup for measurement of AM rejection.

PROCEDURES:

1. Set FM Signal Generator as follows:
Output Frequency = 4.5 MHz
Modulating frequency = 1000 Hz
Deviation = ± 25 kHz
Output level for V_{in} = 100 mV rms
2. Set AM Signal Generator as follows:
Output frequency = 4.5 MHz
Modulating frequency = 1000 Hz
Per cent modulation = 30
Output level for V_{in} = 10 mV rms
3. With S_1 in Position A measure AF Output Voltage and record as $V_o(\text{FM})$.
4. With S_1 in Position B measure AF Output Voltage and record as $V_o(\text{AM})$.
5. Determine AM Rejection from $AMR = \frac{V_o(\text{FM})}{V_o(\text{AM})}$

* TRW Electronics, Des Plaines, Illinois.
Part No. EO23874, or equivalent.

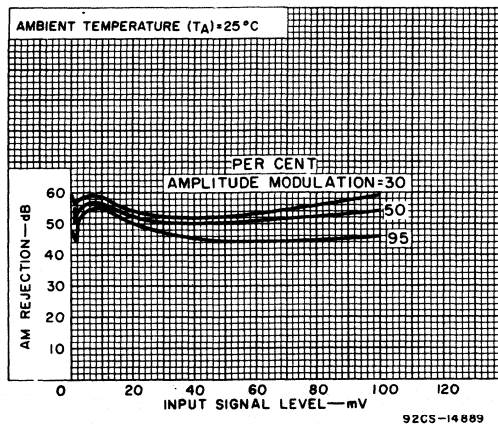
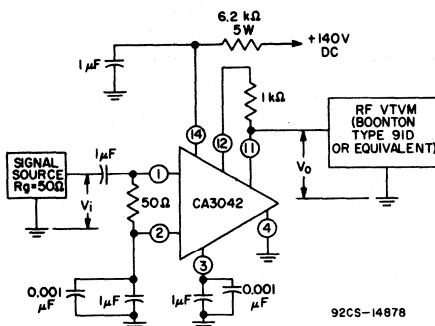


Fig.7 - Typical AM rejection characteristics.



PROCEDURE Voltage Gain:

1. Set input frequency at desired value, $v_i = 100 \mu\text{V rms}$.
2. Record v_o .
3. Calculate Voltage Gain A from $A = 20 \log_{10} v_o/v_i$.
4. Repeat Steps 1, 2, and 3 for each frequency and/or for temperature desired.

Fig.8 - Test setup for measurement of IF amplifier voltage gain.

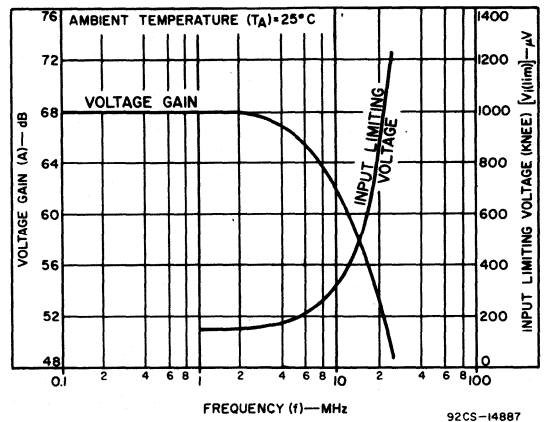


Fig.9 - Typical IF amplifier voltage gain and input limiting voltage (knee) characteristics.

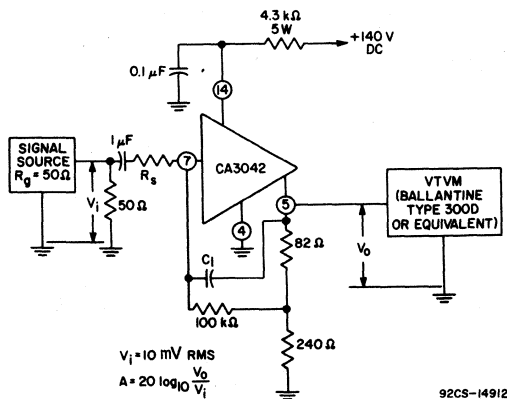


Fig.10 - Test setup for measurement of AF amplifier voltage gain.

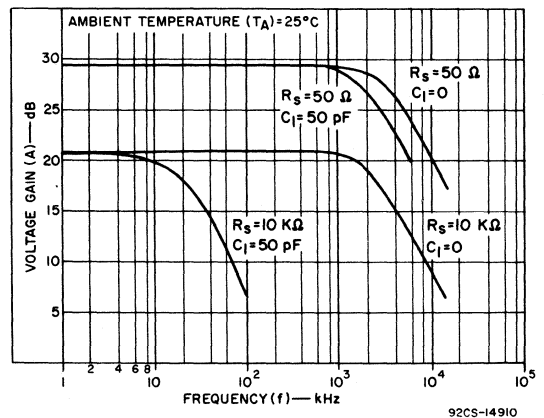
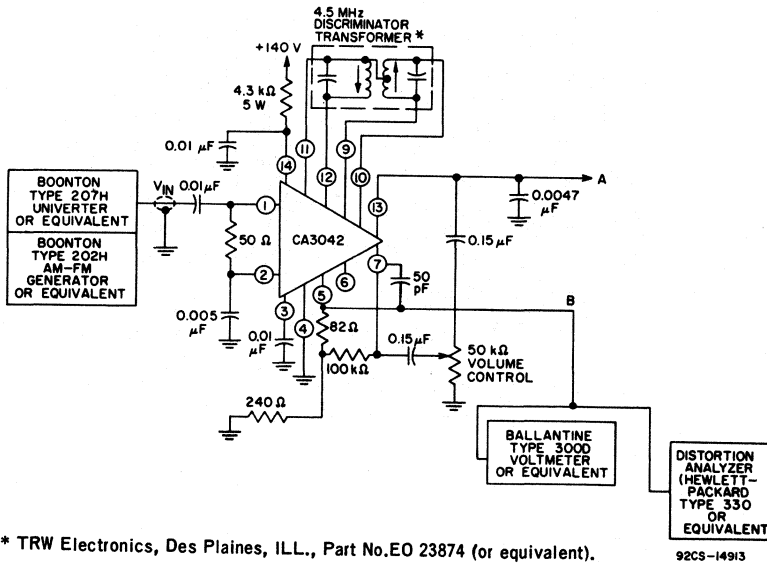


Fig.11 - Typical AF amplifier voltage gain characteristics.

CA3042



PROCEDURES:

Recovered AF Voltage:

1. Set Input Signal Generator as follows:
 - Output frequency = 4.5 MHz
 - Modulating frequency = 1 kHz
 - Deviation = ± 25 kHz
 - Output level for V_{in} = 100 mV rms
2. Set volume control for maximum af output
3. Measure af output voltage and record as Recovered AF Voltage.

Total Harmonic Distortion:

1. Adjust volume control for an af output voltage of 500 mV rms.
2. Measure Total Harmonic Distortion of the output signal in accordance with the Operating Instructions for the Distortion Analyzer.

Input Limiting Voltage (Knee):

1. Decrease V_{in} until the af output voltage is 3 dB less than the value set in Step 1 of the procedure for measurement of Total Harmonic Distortion (500mV - 3 dB = 350 mV)
2. Measure resulting value of V_{in} and record as Input Limiting Voltage (Knee).

Fig.12 - Test setup for measurement of input limiting voltage (knee), recovered AF voltage, and total harmonic distortion.

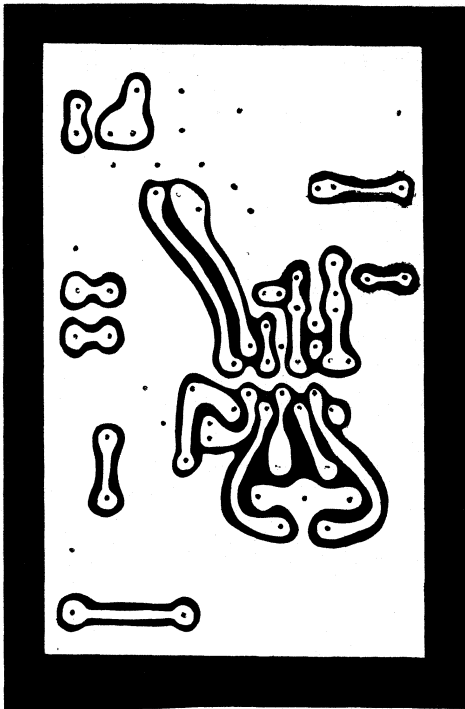


Fig.13 - Recommended layout of printed-circuit board for TV-receiver sound strip utilizing RCA-CA3042. (Actual Size, Bottom View)

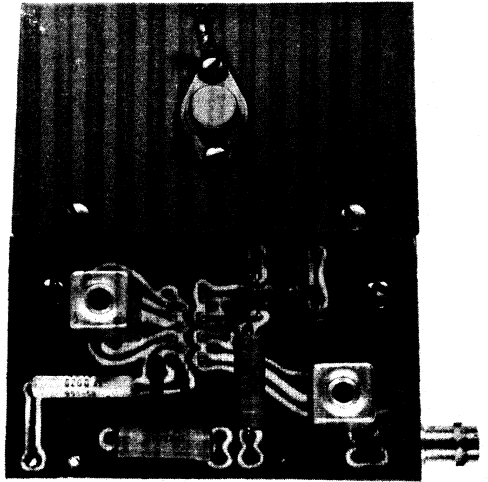
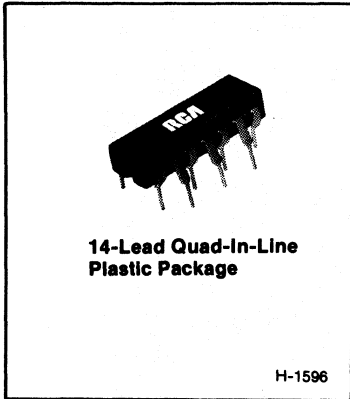


Fig.14 - Recommended parts layout for TV-receiver sound strip utilizing RCA-CA3042. (Top View)

CA3065



IF Amplifier-Limiter, FM Detector, Electronic Attenuator, Audio Driver

For Television Sound-System Applications

Features:

- Electronic attenuator - replaces conventional volume control
- Differential peak detector - requires on single tuned coil
- Internal Zener diode regulated supply
- Inherent high stability
- Excellent AM rejection - 50 dB typ. at 4.5 MHz
- Low harmonic distortion
- High sensitivity - 200 μ V limiting (knee) at 4.5 MHz
- Audio drive capability - 6 mA p-p
- Undistorted audio output voltage - 7 V p-p

The RCA CA3065• Television Sound System is a monolithic integrated circuit which combines a multistage IF amplifier limiter, an FM detector, an electronic attenuator, a zener diode regulated power supply, and an audio amplifier-driver that is designed to directly drive an n-p-n power transistor or high-transconductance tube. Because the circuit is so inclusive, a minimum number of external components is required. A block diagram of the integrated circuit television sound system is shown in Fig. 1.

The CA3065 with its advanced circuit design provides a high-performance multistage subsystem for the sound system of a television receiver. A particular feature of the CA3065 is the electronic attenuator which performs the

conventional volume control function. Volume control is accomplished when the bias levels in the attenuator are changed by means of a variable resistor connected between Terminal 6 and ground (attenuation in excess of 60 dB is attained). Because no audio signal is present in this control, hum or noise pickup can be bypassed. In most cases, only a single unshielded wire is required between the IF board and the variable resistor (volume control).

The CA3065 utilizes a 14-lead dual-in-line plastic package with leads specially formed to facilitate automatic insertion of the device into suitably punched printed-circuit boards.

•Formerly Dev. Type No. TA5814

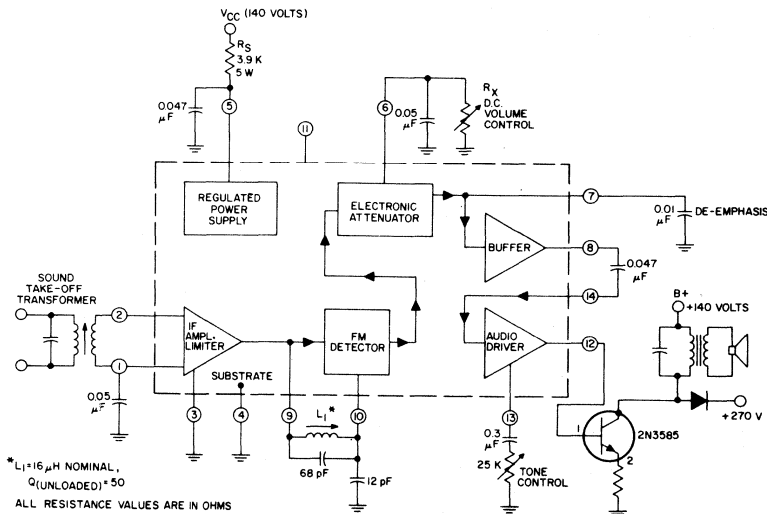


Fig. 1 - Block diagram of CA3065 in a typical circuit application.

92CM-15817R1

MAXIMUM RATINGS, Absolute Maximum Values, at T_A = 25°C

Input Signal Voltage (between Terminals 1 and 2) . . .	±3	V
Power Supply Current (Terminal 5)	50	mA
Power Dissipation:		
Up to T _A = 25°C	850	mW
Above T _A = 25°C	Derate linearly 6.67	mW/°C
Ambient Temperature Range:		
Operating	- 40 to + 85	°C
Storage	- 65 to + 150	°C

MAXIMUM VOLTAGE RATINGS at T_A = 25°C

The following chart gives the range of voltages which can be applied to the terminals listed vertically with respect to the terminals listed horizontally. For example, the voltage range of the vertical terminal 9 with respect to terminal 3 is 0 to +4 volts.

TERMINAL No.	4	5	6	7	8	9	10	11	12	13	14	1	2	3	
4		SUBSTRATE CONNECTION - ALWAYS CONNECT TO TERMINAL 3													
5			+13 0	+13 0	+13 0	*	*	INTERNAL CONNECTION DO NOT USE	+13 0	+13 0	*	*	*	NOTE 1	
6				*	*	*	*		*	*	*	*	*	*	+13 -5
7					+1 -4	*	*		*	*	*	*	*	*	+13 0
8						*	*		*	*	*	*	*	*	*
9							*		*	*	*	*	*	*	+4 0
10									*	*	*	*	*	*	+4 -5
11								INTERNAL CONNECTION DO NOT USE							
12									+4 -1	*	*	*	*	*	
13										*	*	*	*	*	
14											*	*		+3 -5	
1													+5 -5	+5 -5	
2														+4 -5	
3															

MAXIMUM CURRENT RATINGS

TERMINAL No.	I _{IN} mA	I _{OUT} mA
4	SUBSTRATE: CONNECT TO TERMINAL 3	
5	50	1
6	1	1
7	1	1
8	0.5	6
9	1	1
10	1	0.1
11	INT. CONN. DO NOT USE	
12	0.5	6
13	1	2
14	1	0.1
1	1	0.1
2	1	0.1
3	0.1	50

Note 1: Terminal No. 5 may be connected to any positive voltage through a suitable resistor provided that the current and dissipation ratings of the CA3065 are not exceeded.

*Voltages are not normally applied between these terminals. Voltages appearing between these terminals will be safe if specified limits between all other terminals are not exceeded.

Linear Integrated Circuits

CA3065

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V_{CC} = +140\text{V}$ applied to Terminal 5 through $R_S = 3.9\text{ k}\Omega$, and DC Volume Control (R_X) = 0 unless otherwise indicated.

CHARACTERISTIC	SYMBOL	TEST CIRCUIT Fig. No.	SPECIAL TEST CONDITIONS	LIMITS			UNITS
				Min.	Typ.	Max.	
Static Characteristics							
Zener Regulating Voltage Terminal No. 5	V_5	-		10.3	11.2	12.2	V
Current into Terminal 5	I_5	-	Connect Terminal 5 to +9 V	10	16	24	mA
Total Device Dissipation	P_T	-		343	370	400	mW
Terminal Voltages:	1 6 7 9 12	V_1 V_6 V_7 V_9 V_{12}	-	- - - - 4	2 4.8 6.1 3.7 5.1	- - - - 5.8	V
Dynamic Characteristics							
IF AMPLIFIER							
Input Limiting Voltage (at -3 dB point)	$V_{i(\text{lim})}$	3	$f_0 = 4.5\text{ MHz}$, $f_m = 400\text{ Hz}$, Deviation = $\pm 25\text{ kHz}$,	-	200	400	μV
AM Rejection	AMR	3	Amplitude Modulation = 30% $f = 4.5\text{ MHz}$	40	50	-	dB
Transconductance Magnitude	$ G_m $ (IF)	-	$f = 4.5\text{ MHz}$ IF Input Terminals: 2, 1	-	500	-	mmho
Phase Angle	θ (IF)	-	IF Output Terminals: 9, 3	-	46	-	degrees
Feedback Capacitance	C_{fb}	-	$f = 1\text{ MHz}$; Terminals 2 and 9	-	<0.02	-	pF
Input Impedance Components:							
Parallel Input Resistance	R_i (IF)	-	Measured between Terminal Nos. 1 and 2	-	17	-	$\text{k}\Omega$
Parallel Input Capacitance	C_i (IF)	-	$f = 4.5\text{ MHz}$	-	4	-	pF
Output Impedance Components:							
Parallel Output Resistance	R_o (IF)	-	Measured between Terminal No. 9 and gnd	-	3.25	-	$\text{k}\Omega$
Parallel Output Capacitance	C_o (IF)	-	$f = 4.5\text{ MHz}$	-	75	-	pF
DETECTOR							
Recovered AF Voltage	V_o (af)	3	$f = 4.5\text{ MHz}$; $V_i = 100\text{ mV}$ $\Delta f = \pm 25\text{ kHz}$	0.5	0.75	-	V(rms)
Total Harmonic Distortion	THD	3	$f_m = 400\text{ Hz}$	-	0.9	2	%
Output Resistance:							
Terminal 7	R_o	-		-	7.5	-	$\text{k}\Omega$
Terminal 8		-		-	300	-	Ω
ATTENUATOR			See Fig. 7				
Max. Attenuation	-	3	$R_X = \infty$	60	80	-	dB
Max. "Play-through" Voltage*	-	3	$R_X = \infty$	-	0.075	1	mV
AUDIO AMPLIFIER							
Voltage Gain	A (af)	4	$V_i = 0.1\text{ V(rms)}$, $f = 400\text{ Hz}$	17.5	20	-	dB
Total Harmonic Distortion	THD	4	$V_o = 2\text{ V(rms)}$, $f = 400\text{ Hz}$	-	1.5	-	%
Undistorted Output Voltage	-	4	THD = 5%, $f = 400\text{ Hz}$	2	2.5	-	V(rms)
Input Resistance	R_i (af)	-	$f = 400\text{ Hz}$	-	70	-	$\text{k}\Omega$
Output Resistance	R_o (af)	-	$f = 400\text{ Hz}$	-	270	-	Ω

*"Playthrough" voltage is the unwanted signal, measured at Terminal 8, when the volume control is set for minimum output.

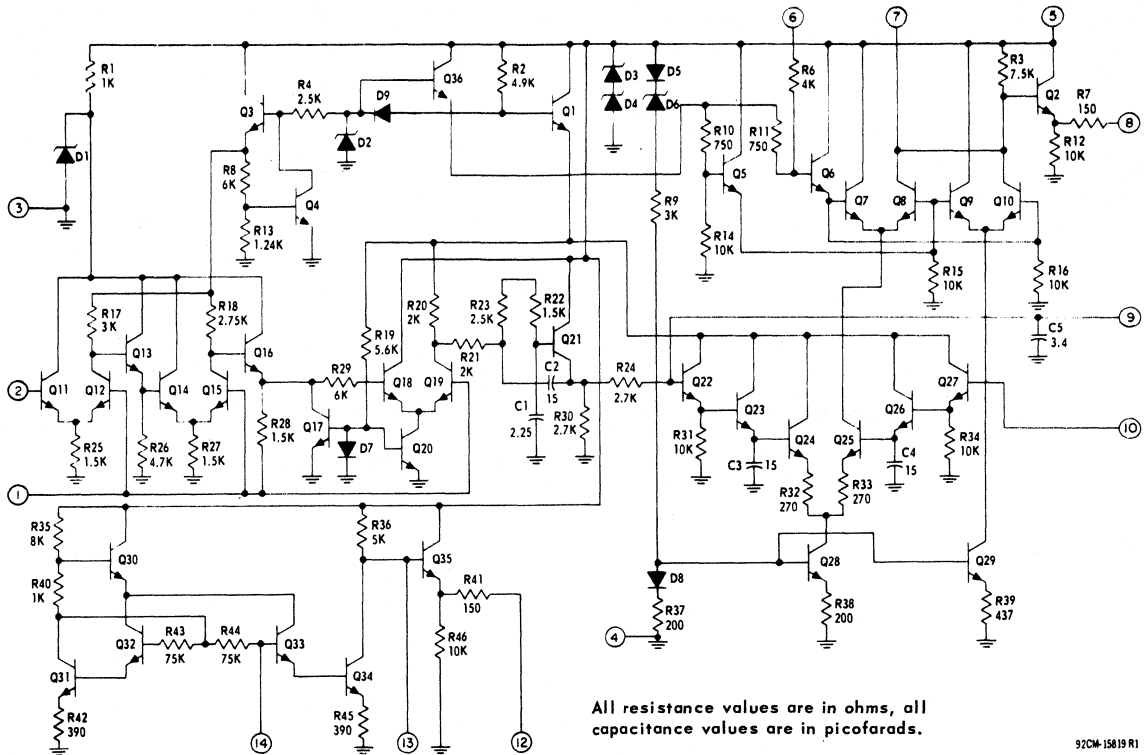


Fig. 2 - Schematic diagram of CA3065

The resistance values included on the schematic diagram have been supplied as a convenience to assist Equipment Manufacturers in optimizing the selection of "outboard" components of equipment designs. The values shown may vary as much as $\pm 30\%$.

RCA reserves the right to make any changes in the Resistance Values provided such changes do not adversely affect the published performance characteristics of the device.

92CM-15819 R1

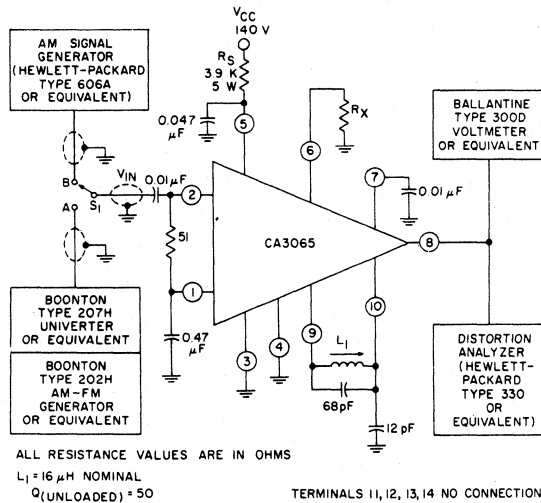


Fig. 3 - Input limiting voltage, AM rejection, re-covered audio, total harmonic distortion, maximum attenuation, maximum "play-through" test circuit.

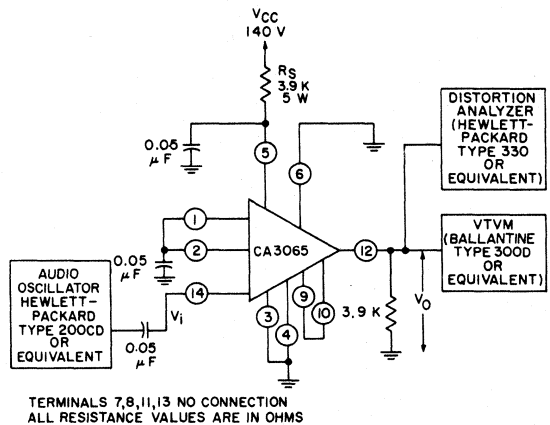
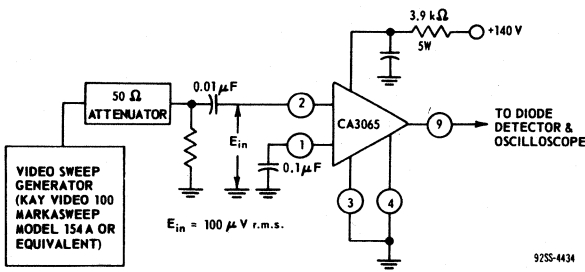


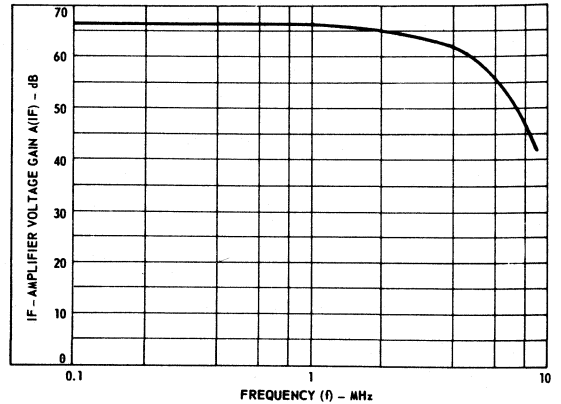
Fig. 4 - Audio voltage gain (undistorted output) test circuit.

Linear Integrated Circuits

CA3065

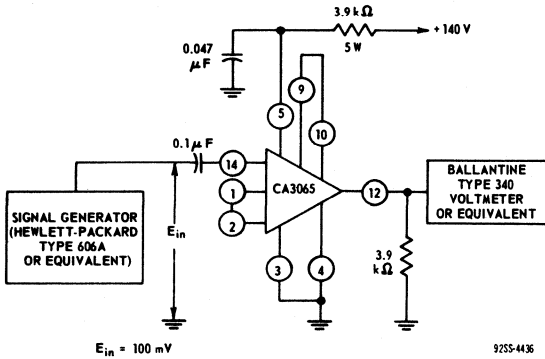


(a) Test circuit

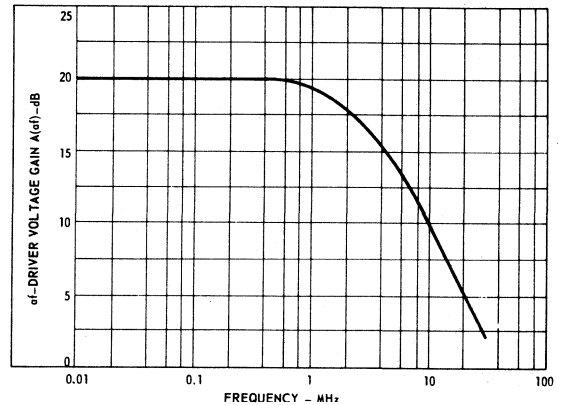


(b) Response curve

Fig. 5 - Frequency response of IF-amplifier section of CA3065



(a) Test circuit



(b) Response curve

Fig. 6 - Frequency response of af-amplifier section of CA3065

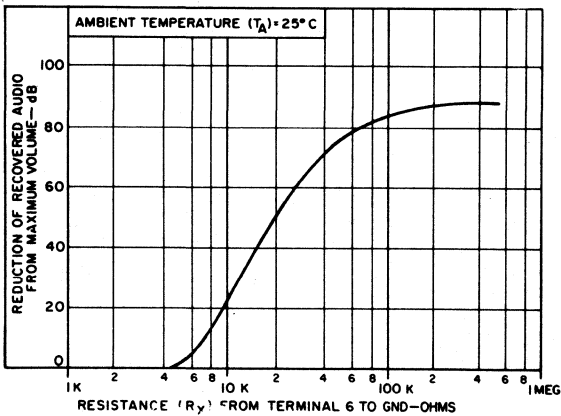
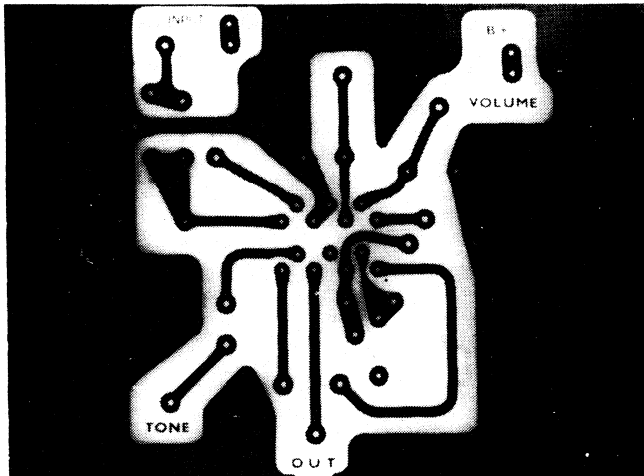


Fig. 7 - Gain reduction vs. resistance (terminal 6 to gnd)

OPERATING CONSIDERATIONS

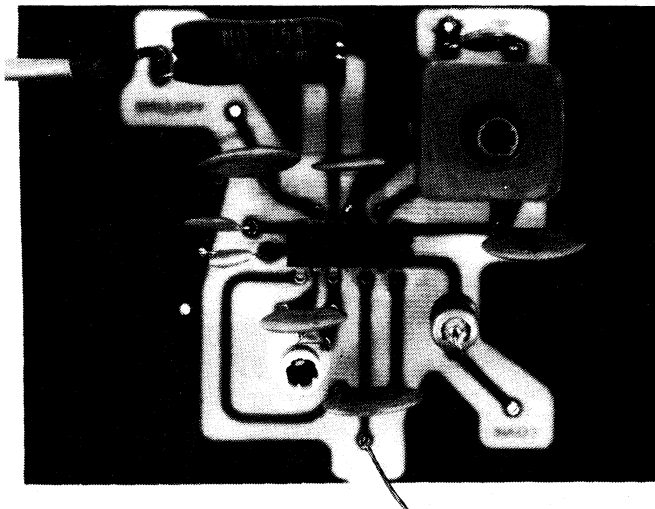
As in all TV receivers, precaution should be taken to prevent destruction of the CA3065 in the event of cascade arcs originating in the picture tube or in the output tube. In the case of arcing in the output tube a resistor of 150k in series with terminal No. 12 and the grid of the tube is usually sufficient protection.

To prevent damage from picture tube arcs, a careful analysis of board layout and coupling modes (electrostatic or magnetic) may be necessary to suggest alternate layouts or appropriate locations for the placement of spark gaps to absorb the high energy discharge.



(a) Printed circuit board - bottom view*
Full Size

92SS-4438



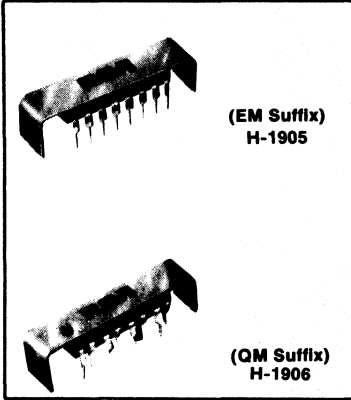
(b) Parts layout - top view*
Full Size

92SS-4439

*Fig. 8 - Recommended parts layout for TV receiver
sound strip using CA3065.*

* A 200 mil square grid was used in the layout of passive components on the printed circuit board. The Quad-in-line formed leads conform to a standard grid spacing of 100 mil centers.

CA3134EM, CA3134QM



TV Sound IF and Audio Output Subsystems

FEATURES:

- Output power 3 W (typ.) at $V^+ = 24\text{ V}$, $R_L = 16\ \Omega$
- Power amplifier with current limiting and thermal shutdown
- Wide power-supply range: 12 V to 33 V
- Low quiescent current: 30 mA typ.
- 5-kHz deviation sensitivity: 1 W output typ.
- 3-dB limiting sensitivity: 200 μV typ.
- Excellent AM rejection: 50 dB typ.
- Differential peak detector — requires one tuned coil
- Electronic volume control with improved taper
- Optional unattenuated audio output
- Optional power-supply ripple by-pass

The RCA-CA3134 combines the sound IF and audio output subsystems on a single monolithic integrated circuit to provide a television sound system for color or black-and-white applications. Each device includes a multistage IF amplifier-limiter, an FM detector, and an audio power amplifier that is designed to drive an 8-, 16-, or 32-ohm speaker.

The CA3134EM and CA3134QM are supplied in the 16-lead plastic "power slab" package with a tin-plated copper strap heat sink attached. The CA3134EM is supplied with dual-in-line leads and the CA3134QM is supplied with dual-quad-formed leads.

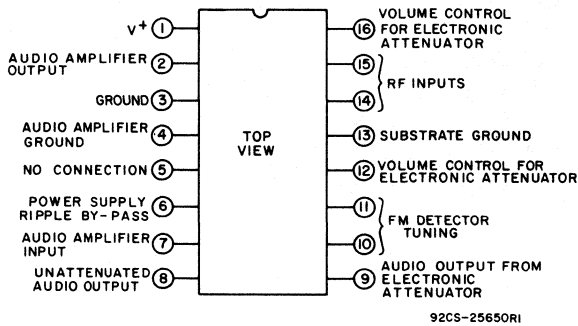


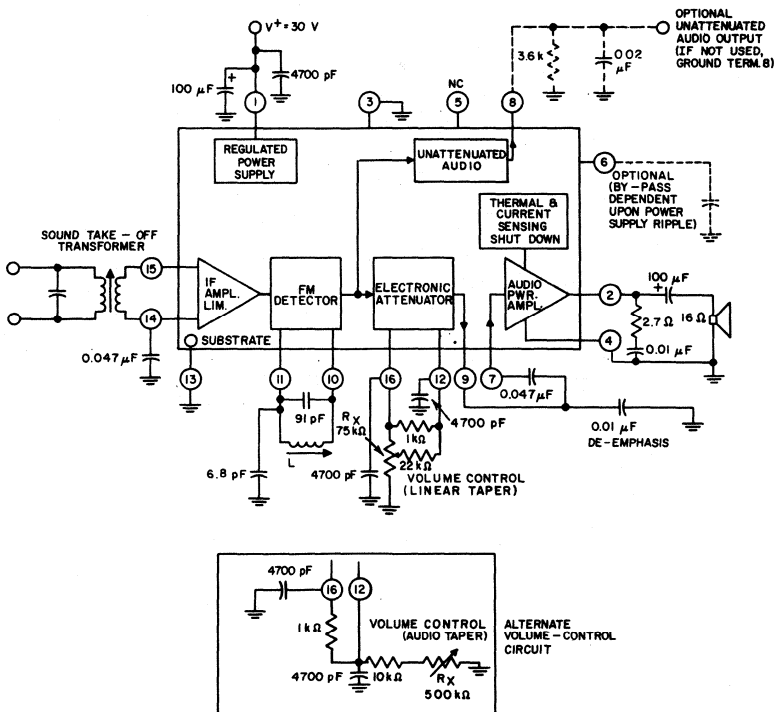
Fig. 1 — Terminal diagram of the CA3134EM, and CA3134QM.

TV/CATV Circuits

CA3134EM, CA3134QM

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE (Between Term. 1, V ⁺ and Terms. 4, audio-output ground and 13, substrate)	33	V
INPUT SIGNAL VOLTAGE (Between Terms. 14 and 15)	± 3	V
DEVICE DISSIPATION:		
With Copper-Strap Heat Sink —		
Soldered to PC Board		
Up to T _A = 25° C	5.0	W
Above T _A = 25° C	40	mW/°C
Unsoldered		
Up to T _A = 25° C	2.9	W
Above T _A = 25° C	24	mW/°C
THERMAL RESISTANCE		
Junction to Slab	5	°C/W
AMBIENT TEMPERATURE RANGE:		
Operating	-40 to +85	°C
Storage	-65 to +150	°C
LEAD TEMPERATURE (During Soldering):		
At a distance 1/16 in. \pm 1/32 in. (1.59 \pm 0.79 mm) from case for 10 seconds max.	+265	°C



92CS-24(35R3)

Fig. 2 - Block diagram of the CA3134 in a typical circuit application.

CA3134EM, CA3134QM

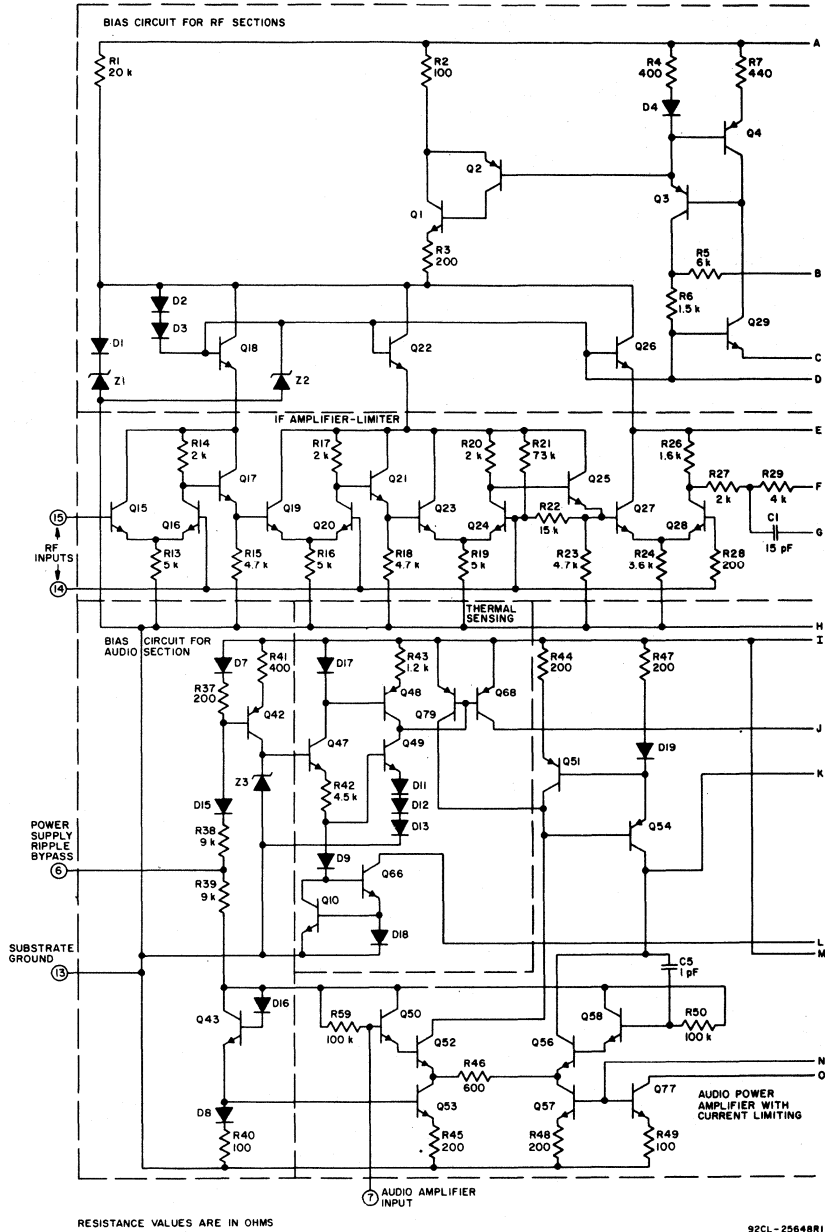
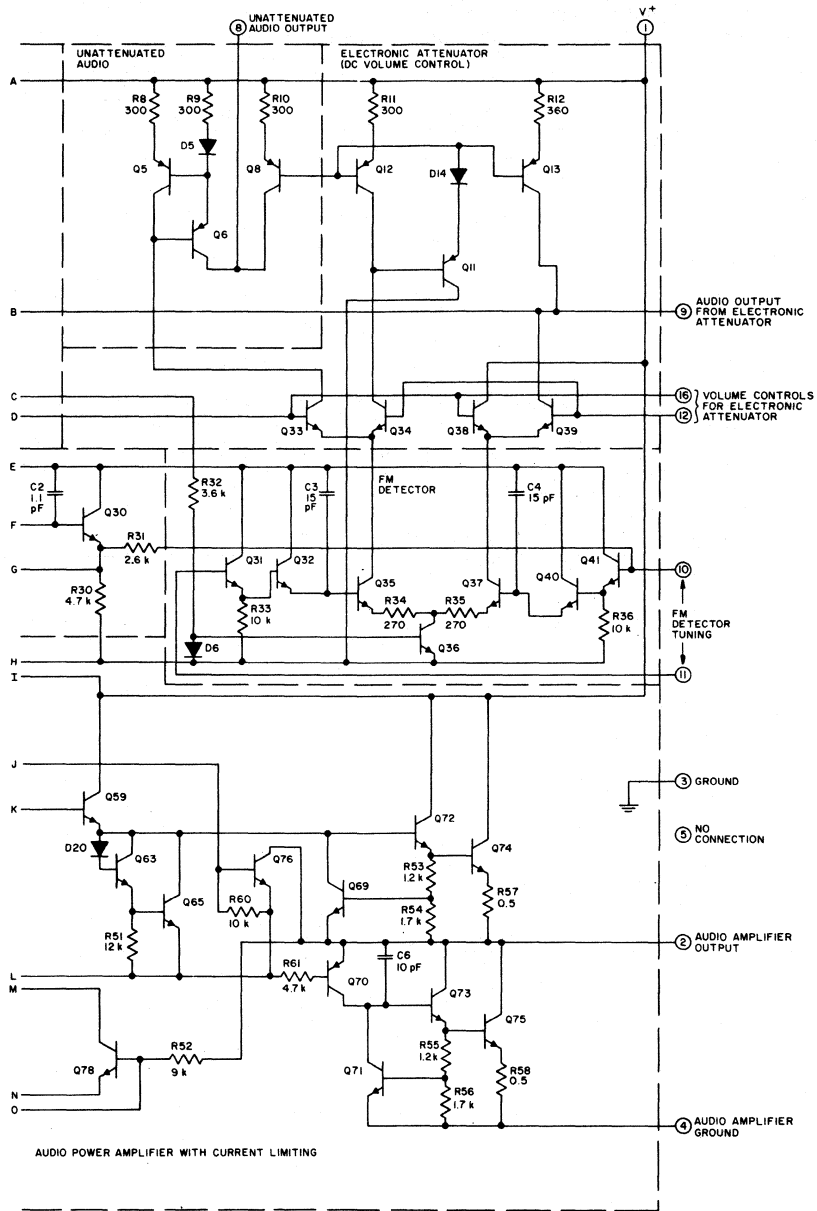


Fig. 3 - Schematic diagram of the CA3134 (cont'd on next page).

TV/CATV Circuits

CA3134EM, CA3134QM



92CL-25648R1

Fig. 3 - Schematic diagram of the CA3134 (cont'd from previous page).

Linear Integrated Circuits

CA3134EM, CA3134QM

ELECTRICAL CHARACTERISTICS

Test Conditions: $T_A = 25^\circ\text{C}$, $V^+ = +30\text{V}$ (applied to Term. 1), DC Volume Control, $R_x = 75\text{ k}\Omega$, $R_L = 16\Omega$, unless otherwise indicated. Refer to Fig. 2

CHARACTERISTIC	SPECIAL TEST CONDITIONS	LIMITS			UNITS
		Min.	Typ.	Max.	
Static Characteristics					
Current into Term. 1, I_1	$P_o = 0$	15	30	45	mA
Dynamic Characteristics					
IF AMPLIFIER:					
Input Limiting Voltage, V_{15} (lim) (at -3 db point)	$f_o = 45\text{ MHz}$ $f_m = 400\text{ Hz}$ $\Delta f = \pm 25\text{ kHz}$	—	200	400	μV
AM Rejection, AMR	$f_o = 4.5\text{ MHz}$, $f_m = 400\text{ Hz}$, Modulation Index = 0.3, $V_{15} = 20\text{ mV}$	40	50	—	dB
Input Resistance, R_i	$V_{15} = 35\text{ mV}$	—	25	—	k Ω
Input Capacitance, C_i	$V_{15} = 35\text{ mV}$	—	3	—	pF
DETECTOR:					
Recovered af Voltage (Term. 9), $V_o(\text{af})$	$f_o = 4.5\text{ MHz}$, $f_m = 400\text{ Hz}$, $\Delta f = \pm 25\text{ kHz}$, $V_{15} = 100\text{ mV}$	—	700	—	mV
Total Harmonic Distortion, (THD)		—	0.8	3	%
Output Resistance, R_o	At Term. 9	—	7.5	—	k Ω
ATTENUATOR:					
Maximum Attenuation	$R_x = 0$	—	10	15	mV
UNATTENUATED AUDIO:					
Recovered af Voltage (Term. 8), $V_o(\text{af})$	$f_o = 4.5\text{ MHz}$, $f_m = 400\text{ Hz}$, $\Delta f = \pm 25\text{ kHz}$, $V_{15} = 100\text{ mV}$	—	600	—	mV
Total Harmonic Distortion(THD)		—	0.8	—	%
AUDIO POWER AMPLIFIER:					
Voltage Gain, $A(\text{af})$	$f = 1\text{ kHz}$	—	35	—	dB
System Total Harmonic					
Distortion	$P_o = 1\text{ W}$ ($I_T = 140\text{ mA typ.}$)	—	1.5	—	%
THD (System)	$P_o = 2\text{ W}$ ($I_T = 180\text{ mA typ.}$)	—	1.6	3	%
Power Output, P_o	THD (System) = 10% ($I_T = 210\text{ mA typ.}$)	—	5	—	W
Input Resistance, ($R_i(\text{af})$)	$f = 1\text{ kHz}$	—	100	—	k Ω

TV/CATV Circuits

CA3134EM, CA3134QM

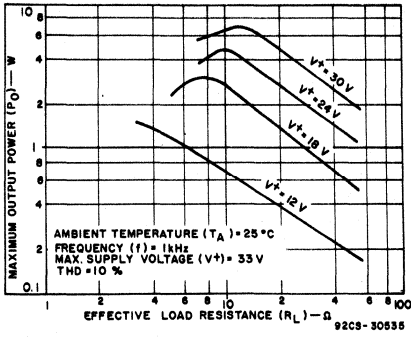


Fig. 4 - Maximum outputpower as a function of effective load resistance.

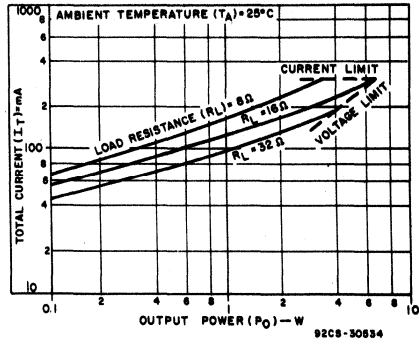


Fig. 5 - Total supply current as a function of output power.

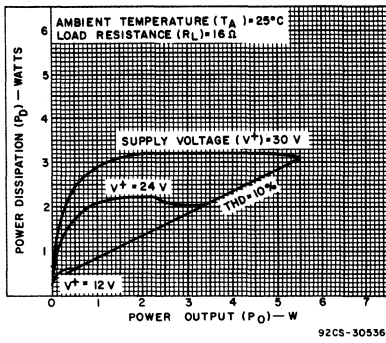


Fig. 6 - Power dissipation as a function of output power.

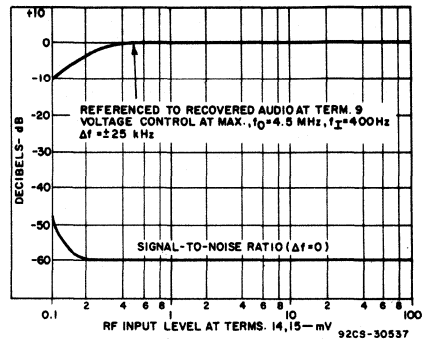
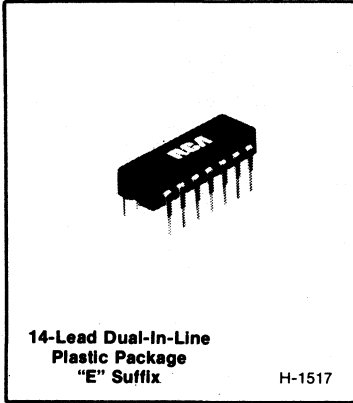


Fig. 7 - Recovered audio, and signal-to-noise ratio as a function of rf input level.

Linear Integrated Circuits

CA3163E



14-Lead Dual-In-Line
Plastic Package
"E" Suffix

H-1517

VHF/UHF Prescaler

Features:

- Broadband operation - 90 to 1000 MHz
- High sensitivity
- Standard 5 V power supply
- Dual mode operation - VHF/UHF
- Complementary ECL outputs
- Independent VHF & UHF input terminals

The RCA-CA3163E* is an integrated-circuit prescaler intended for use in TV frequency synthesis tuning systems over an input frequency range of 90 to 1000 MHz. It performs division by 256 in the uhf mode and division by 64 in the vhf mode.

The mode of operation can be selected by means of the bandswitch and the separate uhf and vhf input terminals provided. The output is a complementary emitter-coupled stage with controlled slew rate for harmonic suppression.

All input terminals should be ac coupled to the appropriate input signal source. Because of high sensitivity, unbuffered coupling from the local oscillator is possible in most cases. In the uhf mode, which is activated by applying a high level to the bandswitch input terminal, all eight divider stages are

operative, resulting in division by 256. In the vhf mode, activated by a low level at the vhf input terminal, two divider stages are bypassed, resulting in division by 64. As a result, approximately the same range of output frequencies are generated for both the uhf and vhf TV bands. An internal amplifier/multiplexer provides this control while isolating both inputs and amplifying the vhf signal. In addition, harmonic output is reduced above 40 MHz by limiting output signal rise and fall times and maintaining a balanced load.

The CA3163E is supplied in the 14-lead Dual-in-Line Plastic Package.

*Formerly RCA Developmental No. TA10535.

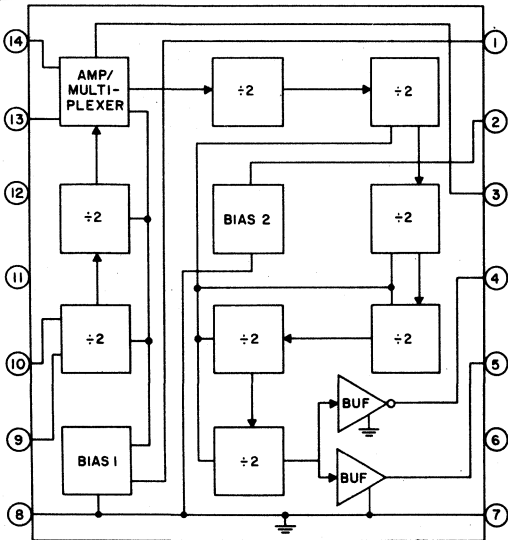
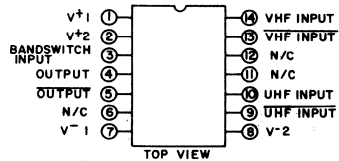


Fig. 1 - CA3163E block diagram.

92CS-31617

TERMINAL DIAGRAM



92CS-30477

N/C=NO CONNECTION

Linear Integrated Circuits

CA3163E

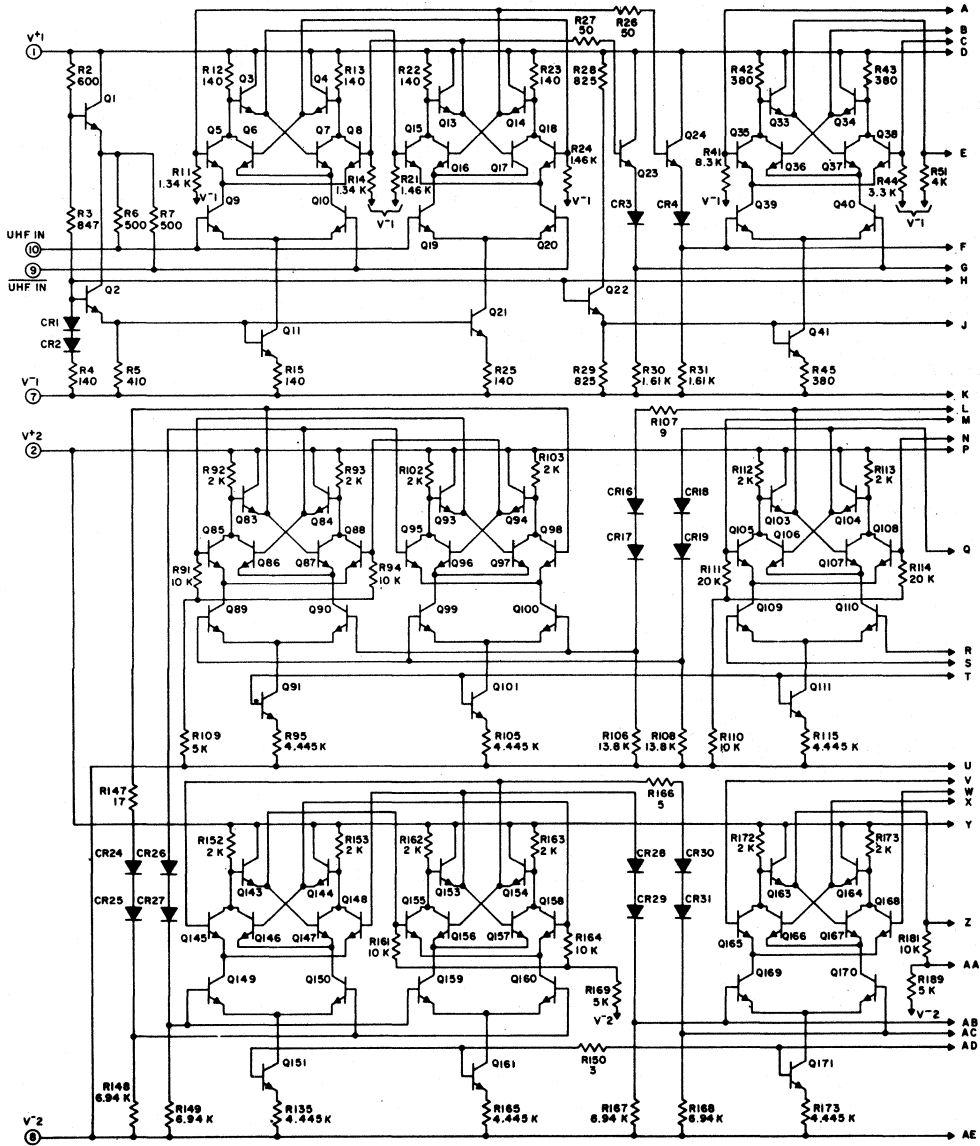


Fig. 3 — Schematic diagram of CA3163E (cont'd. on next page).

92CS-31622

TV/CATV Circuits

CA3163E

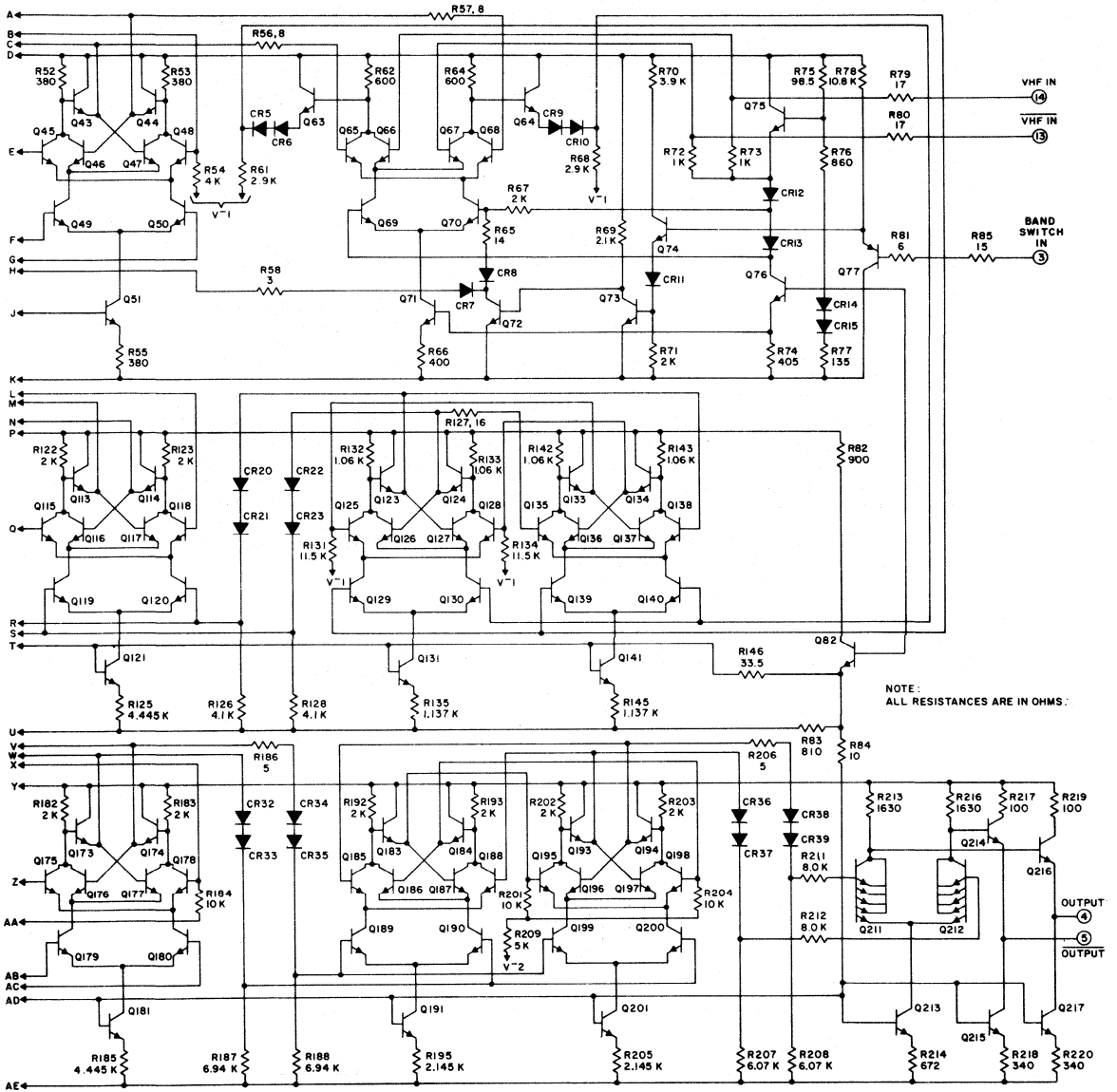
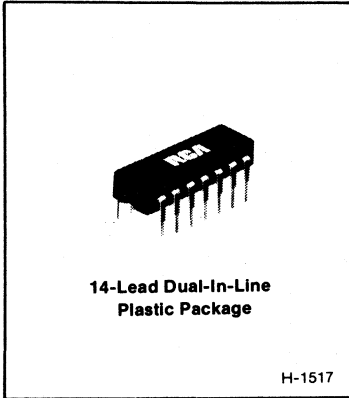


Fig. 3 — Schematic diagram of CA3163E (cont'd. from previous page).

92CL-31622

CA3166E



Operational Amplifier Bandswitch

BiMOS Input Operational Amplifier, Frequency Band-Select Switch, and AFT Mode Switch

For Frequency-Synthesizer Television Tuning Systems

Features:

- Three independent functions - input operational amplifier, AFT mode switch, and band-select switch
- Input operational amplifier has internal biasing circuitry and high-impedance PMOS input transistors
- Internal diode clipper limiting at operational amplifier inputs and short-circuit protection at the outputs
- Static charge protection for both PMOS and CMOS circuit components

The RCA-CA3166E incorporates bipolar, PMOS, and CMOS transistors on a single monolithic chip to provide three functional blocks for use in frequency-synthesizer type TV tuners. Included are an input operational amplifier, a band-select switch, and an AFT mode switch.

The operational amplifier features internal bias and phase compensation, high-impedance PMOS input transistors, diode clipper input limiting, output short-circuit protection, and static charge protection. The operational amplifier is used to amplify an error signal that is proportional to the detected phase difference between the desired channel frequency and an internally generated reference signal. The band-select switch has two logic inputs, a control voltage input, and three outputs (UHF, VHF Low, VHF High) with a drive capability of 90 mA each, for controlling the tuner varactor diodes.

- AFT mode switch utilizes CMOS transmission gate and enable logic input controls AFT mode
- Logic-controlled band-select switch
- Three band-select-switch outputs, each with 90 mA drive capability (typ.) at input voltage up to 28 V dc
- High voltage-rating for wide dynamic control range of error signals and switch functions

The AFT mode switch is a CMOS transmission gate with static charge protection and an enable logic input for selecting the "AFT ON" or "AFT DEFEAT" mode.

The CA3166E is supplied in the 14-lead dual-in-line plastic package.

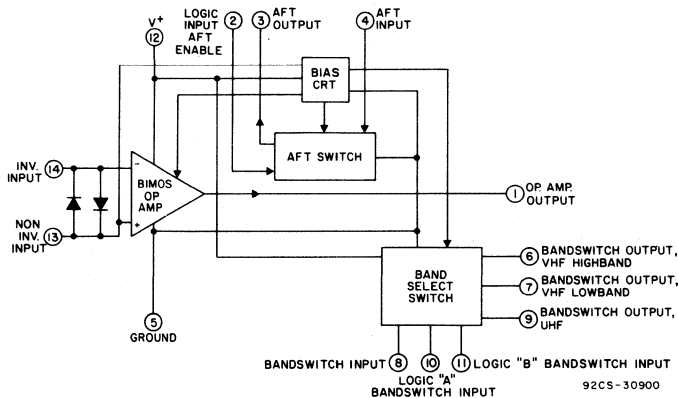


Fig. 1 - CA3166E block diagram.

CA3166E

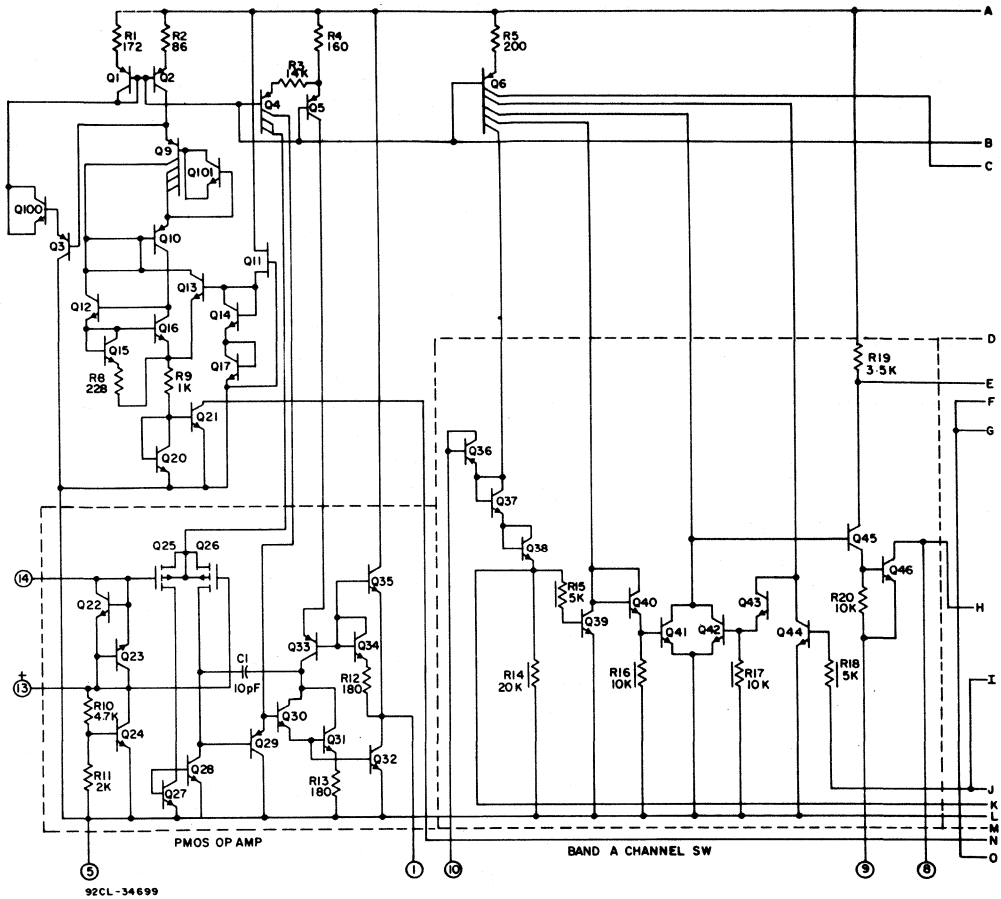


Fig. 2 - Circuit diagram of CA3166E (continued on next page).

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE, V+	+35 V
DIFFERENTIAL INPUT VOLTAGE	±1.5 V
DC SUPPLY CURRENT I+	20 mA
BAND-SELECT SWITCH INPUT VOLTAGE, V _{BS}	+28 V
AFT SWITCH INPUT, OUTPUT	+15 V
CLAMP DIODE CURRENT, OP AMP	±10 mA
BAND SELECT SWITCH SUPPLY CURRENT, I _{BS}	150 mA
DEVICE DISSIPATION:		
Up to +70°C	700 mW
Above +70°C	Derate linearly at 11.1 mW/°C
AMBIENT TEMPERATURE RANGE:		
Operating	0 to +70°C
Storage	-55 to +150°C
LEAD TEMPERATURE (DURING SOLDERING):		
At distance 1/16 ± 1/32 inch (1.59 ± 0.79 mm) from case for 10 s max.	+265°C

CA3166E

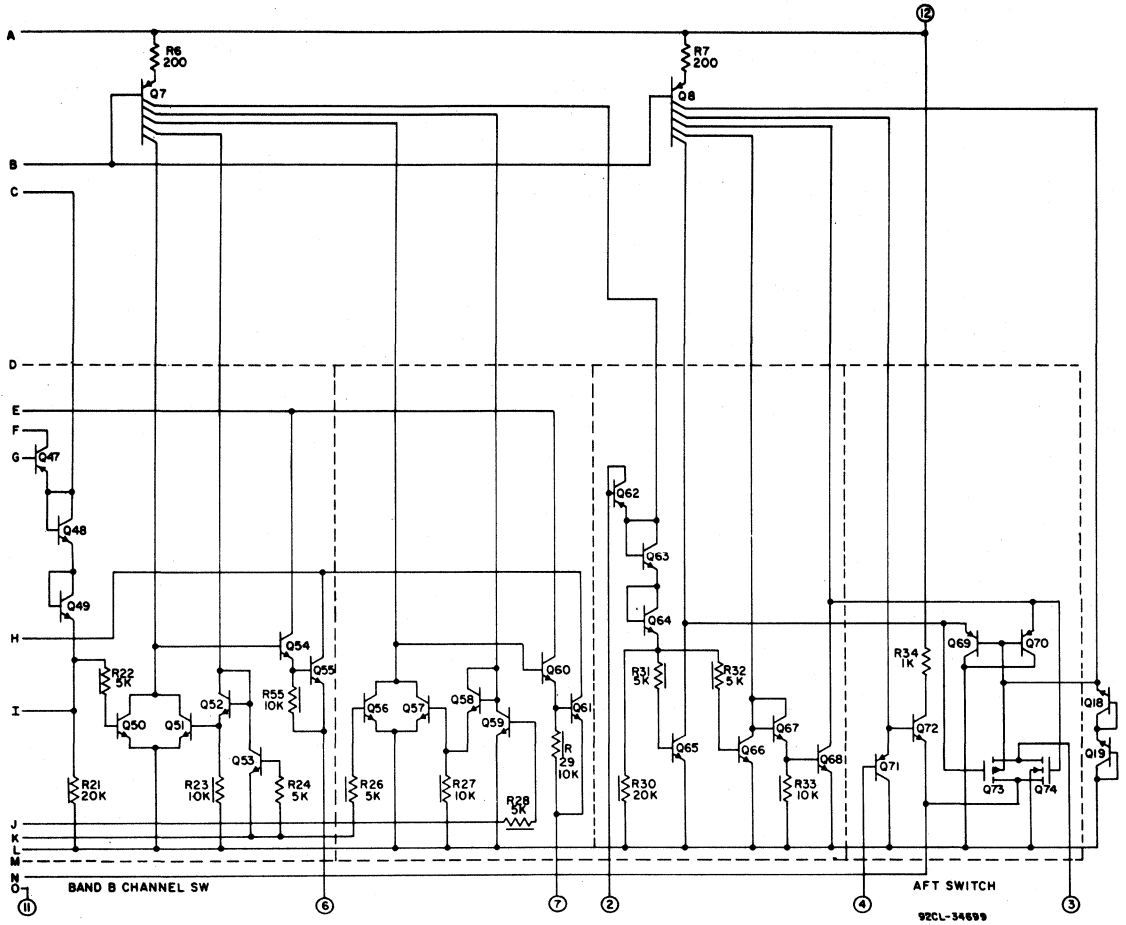
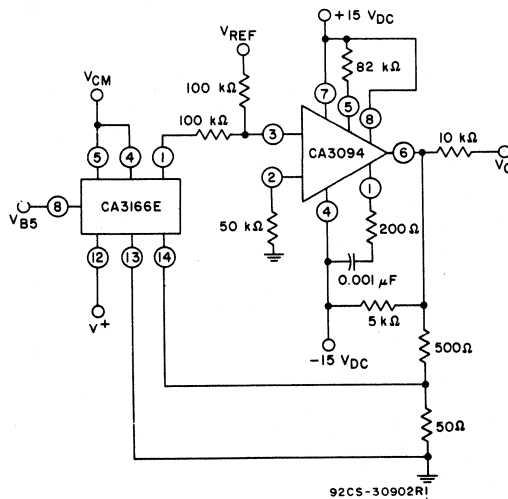


Fig. 2 - Circuit diagram of CA3166E (continued from previous page).

TEST	CONDITIONS (V)			
	V*	V _{CM}	V _{BS}	V _{REF}
V _{O1}	36	0	18	-15
V _{O2}	33	-2	16	-17
V _{O3}	29.5	0	18	-15
V _{O4}	36	0	18	-5



$$CMRR = 20 \log \frac{V_{O1} - V_{O2}}{200}$$

$$PSRR = 20 \log \frac{V_{O1} - V_{O3}}{550}$$

$$AOL = -20 \log \frac{V_{O1} - V_{O4}}{1000}$$

$$V_{IO} = \frac{V_{O1}}{10}$$

Fig. 3 - Operational amplifier test circuit for CMRR, PSRR, AOL, and V_{IO}.

Operational Amplifier (See Fig. 3)

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V_+ = 32.5\text{ V}$, $V_{BS} = 18\text{ V}$, Terms 4 & 5 grounded.

Unless otherwise specified

CHARACTERISTICS	TEST CONDITIONS	LIMITS			UNITS
		MIN.	TYP.	MAX.	
Input Bias Voltage, V_{I3}	$I_{I3} = 4\text{ mA}$, Feedback = $1\text{ M}\Omega$	2.2	2.5	3	VDC
Input Bias Voltage, V_{I3}	$I_{I3} = 6\text{ mA}$, Feedback = $1\text{ M}\Omega$	2.2	2.6	3	
Input Bias Voltage, V_{I4}	$I_{I4} = 1\text{ M}\Omega$, Feedback = $1\text{ M}\Omega$	2.75	3.3	3.75	
Diode Voltage (term. 14 to term. 13)	$I_{I4} = 4\text{ mA}$, Term. 13 = Reference	—	0.8	1	
Diode Voltage (term. 13 to term. 14)	$I_{I3} = 4\text{ mA}$, Term. 14 = Reference	—	0.8	1	
Output Voltage Low, V_{OL} (V_1)	$I_{I4} = 4\text{ mA}$, Resistance between Terms. 1 and 12 = $10\text{ k}\Omega$	—	0.2	0.6	
Output Voltage High, V_{OH} (V_1)	$V_{I4} = 0\text{ V}$, $I_{I3} = 4\text{ mA}$, Resistance between Terms. 1 and 12 = $10\text{ k}\Omega$, $V_+ = 29.5\text{ V}$	27.4	28	—	
Input Offset Voltage, V_{IO}	See Fig. 3	—	10	80	mV
Supply Current, I_+ (I_{I2})	$V_4 = 1\text{ V}$, Feedback (Terms. 1 to 14) = $1\text{ M}\Omega$, $V_+ = 35\text{ V}$, $V_{I3} = 0\text{ V}$	5	14	20	mA
Output Sink Current, I_{OL}	$I_{I4} = 4\text{ mA}$, $V_1 = 32.5\text{ V}$	5	25	—	
Output Source Current, I_{OH}	$I_{I3} = 4\text{ mA}$, $V_1 = V_{I4} = 0\text{ V}$	—	-15	-5	
Input Bias Current, I_{IB} (term. 14)	$V_{I3} = 0\text{ V}$, Term. 1 connected to Term. 14	—	0.5	10	nA
Common-Mode Rejection Ratio, CMRR	See Fig. 3	55	65	—	dB
Power Supply Rejection Ratio, PSRR	See Fig. 3	65	75	—	
Open-Loop Voltage Gain, AQL	See Fig. 3	65	80	—	

Bandswitch Truth Table

LOGIC INPUTS		OUTPUTS		
A	B	UHF	VHF LOW	VHF HIGH
0	0	0	0	0
0	1	0	1	0
1	0	0	0	1
1	1	1	0	0

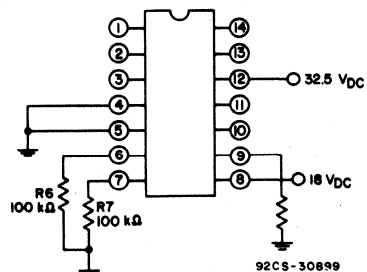


Fig. 4 - Bandswitch test circuit.

Linear Integrated Circuits

CA3166E

Band-Select Switch (See Fig. 4)

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V_+ = 32.5\text{ V}$, $V_{BS} = 18\text{ V}$

Terms. 4 & 5 grounded Terms. 6, 7, 9 = $100\text{ k}\Omega$ to ground. Unless otherwise specified

CHARACTERISTICS	TEST CONDITIONS	LIMITS			UNITS	
		MIN.	TYP.	MAX.		
Logic Inputs "A" & "B" Sink Current (Low)	$V_{10} = V_{11} = 0.6\text{ V}$	-200	-100	—	μA	
Logic Inputs "A" & "B" Source Current (High)	$I_g = -90\text{ mA}$, $V_{10} = V_{11} = 2.4\text{ V}$	-150	5	150		
Output Leakage Current, Terms. 6, 7, 9		—	2	7		
Output Saturation Voltage: (Pin 8 Ref)	Term. 9	$I_g = -90\text{ mA}$, $V_{10} = V_{11} = 2.4\text{ V}$	-1.3	0.6	—	V
	Term. 9	$I_g = -60\text{ mA}$, $V_{10} = V_{11} = 24\text{ V}$	-0.9	0.3	—	
	Term. 7	$I_7 = -90\text{ mA}$, $V_{10} = 0\text{ V}$, $V_{11} = 24\text{ V}$	-1.3	0.6	—	
	Term. 7	$I_7 = -60\text{ mA}$, $V_{10} = 0\text{ V}$, $V_{11} = 2.4\text{ V}$	-0.9	0.3	—	
	Term. 6	$I_6 = -90\text{ mA}$, $V_{10} = 2.4\text{ V}$, $V_{11} = 0\text{ V}$	-1.3	0.6	—	
	Term. 6	$I_6 = -60\text{ mA}$, $V_{10} = 24\text{ V}$, $V_{11} = 0\text{ V}$	-0.9	0.3	—	
Logic Inputs, $V_{IN} (0)$		-0.6	—	0.6		
Logic Inputs, $V_{IN} (1)$		2.4	—	8.5		

AFT Mode Switch

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V_+ = 32.5\text{ V}$, $V_{BS} = 18\text{ V}$

Terms 5, 10, 11 grounded. Unless otherwise specified

CHARACTERISTICS	TEST CONDITIONS	LIMITS			UNITS
		MIN.	TYP.	MAX.	
Logic Input Current Low	$V_2 = 0\text{ V}$, $R_{TERMS. 3} = 100\text{ M}\Omega$, $V_4 = 13.5\text{ V}$	-200	-100	—	μA
Logic Input Current High	$V_2 = 2.4\text{ V}$, $R_{TERMS. 3} = 1\text{ k}\Omega$, $V_4 = 1\text{ V}$	-150	2	150	
Input Current, I_4	$V_2 = 0\text{ V}$, $R_{TERMS. 3} (\text{Open})$, $V_4 = 13.5\text{ V}$	—	2	20	
Output Leakage Current, I_3	$V_2 = 0.6\text{ V}$, $V_3 = 8\text{ V}$, $V_4 = 0\text{ V}$	—	1	100	nA
Output Rev. Current, I_3	$V_2 = 3\text{ V}$, $V_3 = 1.8\text{ V}$, $V_4 = 0\text{ V}$	1.4	2	—	mA
Output Offset Voltage	$V_2 = 3\text{ V}$, $V_4 = 3\text{ V}$, $V_+ = 29.5\text{ V}$	—	0.1	—	V
AFT Switch Resistance	$V_2 = 2.4\text{ V}$	—	800	—	Ω
Logic Input, $V_{IN} (0)$		-0.6	—	0.6	V
Logic Input, $V_{IN} (1)$		2.4	—	8.5	

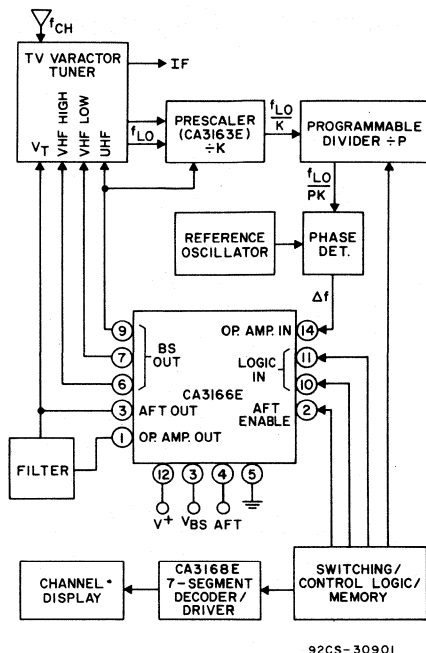


Fig. 5 - Block diagram of a typical digital tuning system.

Tuner Operation

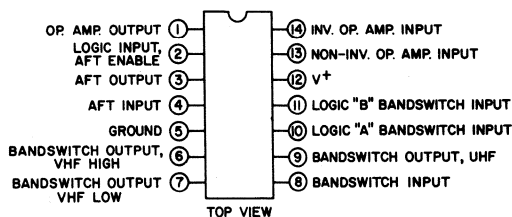
Fig. 5 shows a typical digital TV tuning system employing the CA3166E. This system consists of a phase-locked loop (PLL) and a programmable divider to generate a tuner local-oscillator frequency that is an integral multiple of a reference-oscillator frequency. The output of the local oscillator is connected to a prescaler (CA3163) which divides the frequency to values that can be processed by a programmable divider. The amount of division is established by the control logic and depends on the desired channel to be viewed. This signal and a reference signal are combined in a phase detector to produce an error signal proportional to the frequency separation. The error is then amplified by the CA3166E and filtered to provide a dc voltage to the

varactors of the tuner voltage-controlled oscillator (VCO). The VCO frequency is thus corrected to reduce its difference with the reference.

Logic-control signals are applied to terminals 10 and 11 (band-select switch) of the CA3166E, and the proper varactor circuits for UHF, low-band VHF, or high-band VHF are selected. The truth table for the selection logic is shown on page 4.

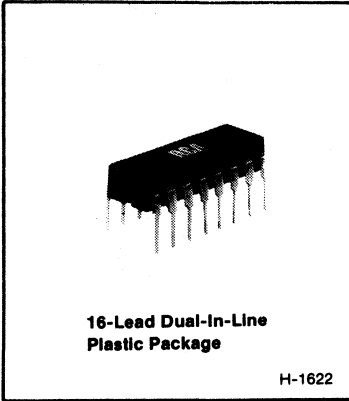
An analog switch for AFT operation is included in the CA3166E for automatic correction of frequency transmission errors.

CA3166E TERMINAL ASSIGNMENT



92CS-30903

CA3215E



FM-IF Amplifier/Detector Limiter

Features:

- Ideal for video disc playback systems
- Phase lock loop FM detector
- Linear detection for large deviation at video modulating frequencies
- Carrier defect detector
- Squelch circuitry
- Loss of carrier latch circuitry

The RCA CA3215E[®] monolithic integrated circuit provides a system for large-deviation FM detection. The device includes a two-stage limiter/amplifier, phase detector, voltage controlled oscillator, wide-band amplifier, carrier defect detector, and output squelch. The phase detector and VCO are connected to form a phase-lock-loop detector capable of recovering wide deviation modulating signals.

The carrier defect detector provides a logic output signal to control corrective circuitry in the event of an instantaneous loss or serve distortion of the carrier signal. The wide-band amplifier is squelched by the same defect detector output or may be squelched by an external input to the device. In the event of longer duration carrier loss, a latch condition will maintain the amplifier in the squelched condition.

*Formerly RCA Dev. Type No. TA10641.

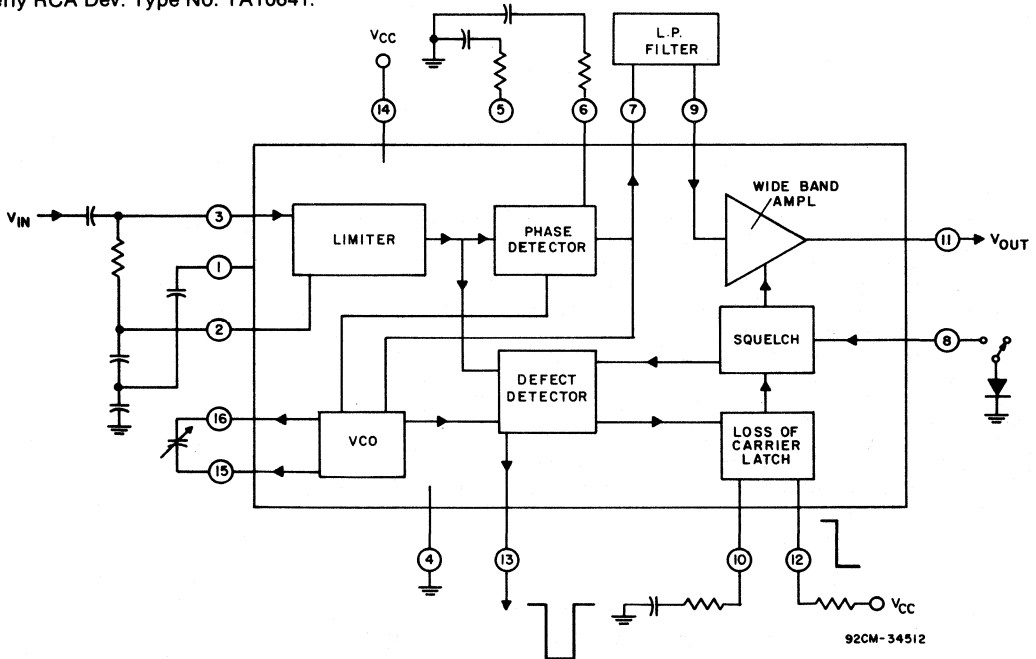


Fig. 1 - Block diagram of the CA3215E.

CA3215E

The RCA CA3215E is intended for use as the video and audio demodulators for video disc playback. It can operate over the temperature range of -40°C to +85°C.

The CA3215E is supplied in the 16-lead dual-in-line plastic package.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE: (Pins 12 or 14 to 4)	16 V
DEVICE DISSIPATION: Up to T _A = 60° C	600 mW
Above T _A = 60° C	Derate linearly at 6.7 mW/° C
AMBIENT TEMPERATURE RANGE: Operating	-40 to +85° C
Storage	-65 to +150° C
LEAD TEMPERATURE (During Soldering): At distance not less than 1/32" (0.79 mm) from case for 10 seconds max.	+265° C

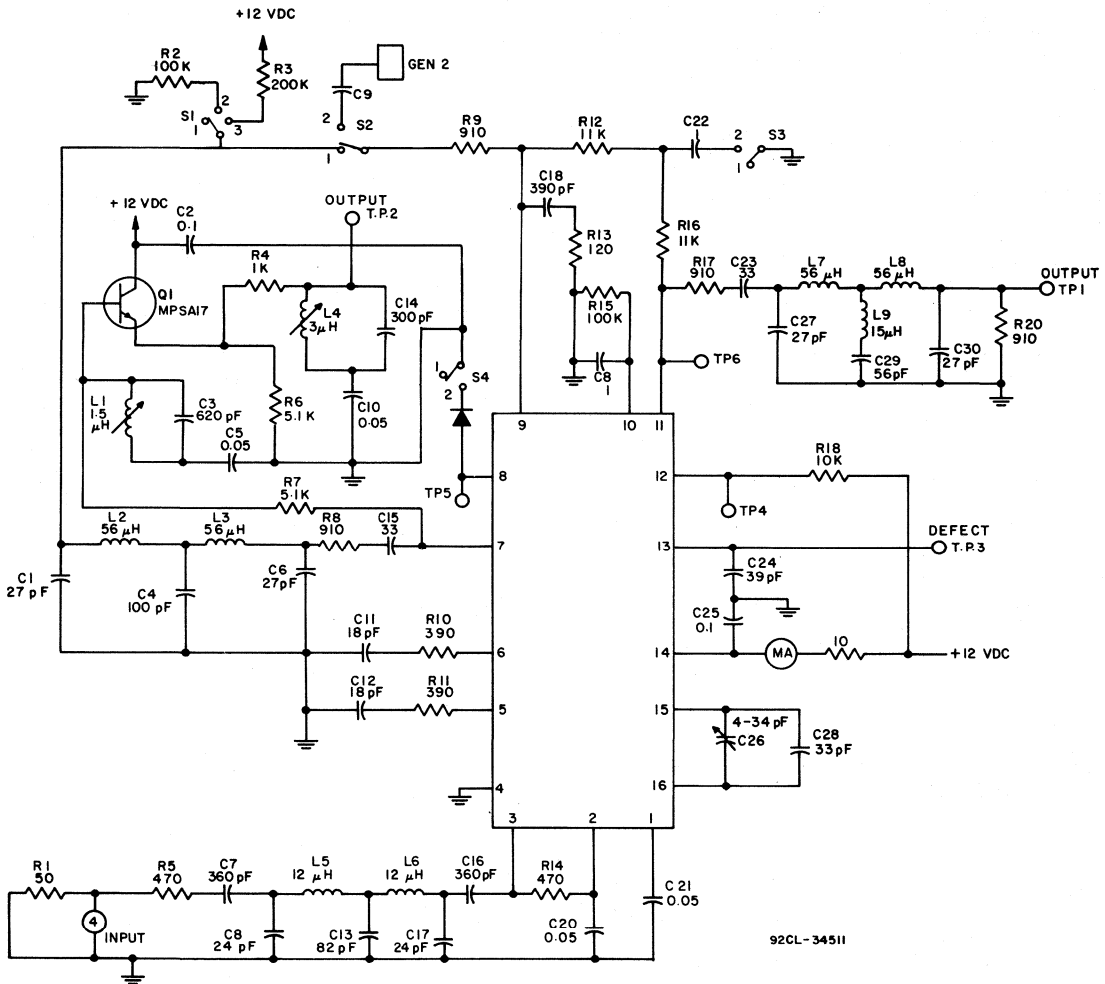
ELECTRICAL CHARACTERISTICS at T_A = 25° C, V₊ = 12 Volts

CHARACTERISTIC	LIMITS			UNITS
	MIN	TYP	MAX	
Static (DC) Characteristics				
Quiescent Current I ₁₄	21	28	35	mA
DC Voltage				V
Terminals 1, 2, and 3	3	3.4	4	
Terminals 9 and 11	5.4	5.8	6.3	
Terminal 8	4	4.3	4.7	
Terminal 13		5.8		
Terminal 7		6.5		
Dynamic Characteristics				
Conditions: F Input = 5 MHz, F mod. = 400 Hz, Deviation = ±1 MHz				
See Figure 2 for test circuit				
Input limiting voltage for -3 dB output (TP1)			5	mVrms
Demodulated Output (TP1)	110		240	mVrms
Total Harmonic Distortion, THD (TP1)			2.5	%
Noise (3 MHz BW) (TP1)		1		mVrms
Open Loop Gain * (Pin 9 to P11) (TP1)		66		x
3 MHz response ** (TP1)		3		dB
5 MHz suppression *** (TP2) no modulation		-40		
Squelched demod. output (TP1)		-55		
Squelched DC shift **** (TP6)			±350	mVDC

- * Use Gen 2 at f = 10,000 Hz; S3 closed
- ** F mod = 3 MHz; compare reading to demod. output
- *** Close S4; compare reading to demod. output
- **** Change in Pin 11 DC voltage under squelched and non-squelched condition

Linear Integrated Circuits

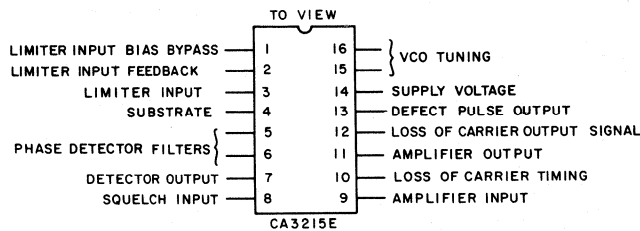
CA3215E



92CL-34511

All capacitances are in μF unless otherwise noted.

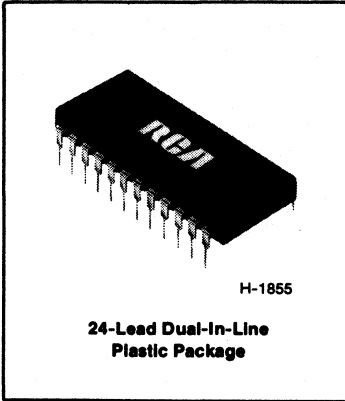
Fig. 2 - Test circuit.



92CS-34513

TERMINAL DIAGRAM

Chroma Processor



Features

- Voltage controlled oscillator with wide deviation and constant output voltage
- All frequency conversion on single chip
- Phase lock loop control and timing correction
- Keyed phase detector

The RCA CA3216E* monolithic integrated circuit provides the primary functions of converting a "buried subcarrier" video signal to a standard NTSC format. Fig. 1 shows a block diagram of the CA3216E which includes a voltage controlled oscillator, reference oscillator, two mixer stages, two wide-band amplifiers, a phase detector and output circuit, a summing circuit, sync separator, sync clamp and keying circuits, and voltage sensing and clamp circuits.

The CA3216E takes the separated chrominance signal at a lower frequency and converts it to the standard TV format and recombines it with the separated luminance signal. The

necessary timing correction is provided via a phase lock loop correction of the voltage controlled oscillator driving the mixers and the sync keying functions. A separate signal controlled by the PLL is provided for other clocking functions. External circuitry with the phase detector, VCXO and mixer form the phase lock loop. All frequencies are determined by external inputs or components.

The CA3216E utilizes the 24-pin dual-in-line plastic package and can operate over the temperature range of -40°C to $+85^{\circ}\text{C}$.

* Formerly Developmental Type No. TA10642.

MAXIMUM RATING, Absolute-Maximum Values:

DC SUPPLY VOLTAGE:

(Terminal 19 to Terminal 8) 16 V

DEVICE DISSIPATION:

Up to $T_A=75^{\circ}\text{C}$ 650 mW

Above $T_A=75^{\circ}\text{C}$ Derate linearly 8.7 mW/ $^{\circ}\text{C}$

AMBIENT TEMPERATURE RANGE:

Operating -40 to $+85^{\circ}\text{C}$

Storage -65 to $+150^{\circ}\text{C}$

LEAD TEMPERATURE (During Soldering):

At distance $1/16 \pm 1/32$ in. (1.59 ± 0.79 mm) from case for 10 seconds max. $+265^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS at $T_A=25^\circ\text{C}$, $V_+=12\text{V}$

CHARACTERISTIC	LIMITS			UNITS
	Min.	Typ.	Max.	
STATIC				
Supply Current	28	40	52	mA
DC Voltage				
Terminal 2	4.6	5.1	5.6	V
Terminal 3	6.5	7	7.5	V
Terminal 4	3.1	3.5	3.9	V
Terminal 5	6.6	7	7.4	V
Terminal 7	1.9	2.2	2.5	V
Terminal 9	3.1	3.5	3.9	V
Terminal 21	6.4	6.9	7.4	V
Terminal 24	6.5	7	7.5	V
DYNAMIC				
Test Condition: See Fig. 2; Dynamic Test Circuit				
V_{OUT} at TP3 (Term. 11) Freq.=1.53 MHz	200	265	330	mV rms
V_{OUT} at Term. 10, Freq.=3.58 MHz	340	415	540	mV rms
Chroma Gain (Term. 4 to Term. 2) Freq.=3.58 MHz	1.15	1.40	1.65	x
Luminance Output (Term. 21)	2.6	2.8	3	V_{p-p}
Luminance Output (Term. 2)	1.9	2	2.1	V_{p-p}
VCXO Offset (Term. 16 to Term. 17) TPI to Term. 5, RX=0, θ (Term. 9)=0	-100	0	+100	mV
VCXO Gain (Term. 18 at F_2 -Term. 18 at F_3) TPI to Term. 5: RX=3000 Ω	0.63	1	1.35	V
VXCO Frequency Deviation (TP3) TPI=V Term. 5 \pm 50 mV; RX=470 Ω ; θ (Term. 9)=0	10	11.5	13	kHz
Spurious Voltage at Term. 2 at Freq.=1.53 MHz; θ (Term. 9)=90 mV rms	—	—	7.5	mV rms
at Freq.=3.58 MHz θ (Term. 9)=0	—	—	4	mV rms
at Freq.=5.11 MHz; θ (Term. 9)=90 mV rms	—	—	90	mV rms

CA3216E

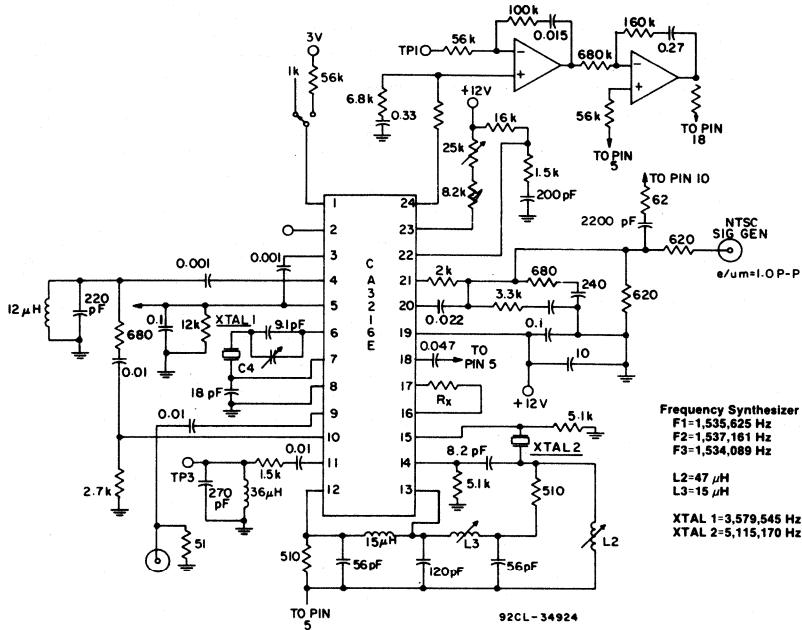
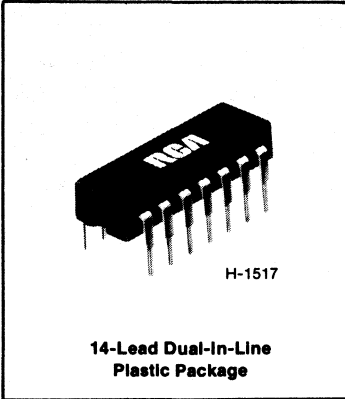


Fig. 2 - Dynamic test circuit.



CMOS DAXI Buffer

The Digital Auxiliary Information (DAXI) Buffer Interfaces a Microprocessor to a Video Disc Player

Features

- Low-level video signal conversion to CMOS logic level
- Converts sine-wave color subcarrier into square-wave for system clock
- Microprocessor compatible external low rate clock
- Cyclic-Redundancy-Check circuit
- For digital microprocessor interfacing to a video disc player analog system

The RCA-CD3226E CMOS IC is a digital auxiliary information (DAXI) buffer which interfaces the digital microprocessor to the analog system of a video disc player. The DAXI code, inserted onto line 17 of each TV field on the video disc, is decoded by the buffer, and this information is fed to the microprocessor which controls the movement of the video disc player.

A 1.53-MHz sine-wave color subcarrier input is used as the CD3226E system clock which shifts in 77 bits binary code, in a string for each TV field, to the registers in the device. When the Control In is high, the error check circuit provides

a high signal at the Status Out to the microprocessor. The microprocessor then brings the Control In to a low and sends a low rate clock to the External Clock In. Correct DAXI data bits, stored in the device registers, are then shifted via the Data Out terminal into the microprocessor. The data contains 18 field number bits and 6 band number bits. If needed, 27 unused bits of DAXI code are available for additional player functions.

The CD3226E is supplied in the 14-lead dual-in-line plastic package.

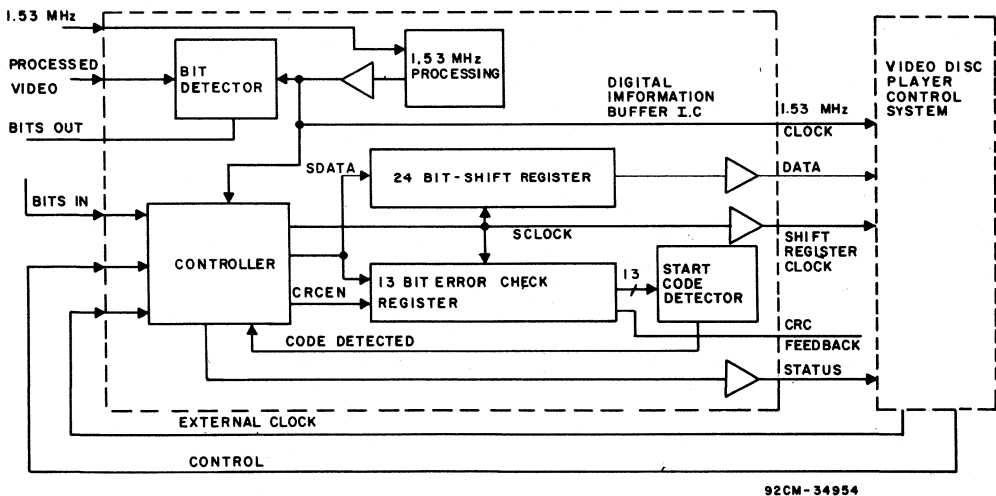


Fig. 1 - CD3226E block diagram.

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CD3226E

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V_{DD}) -(Voltage referenced to V_{SS} Terminal)	-0.5 to +6 V
INPUT VOLTAGE RANGE, ALL INPUTS	-0.5 to $V_{DD} + 0.5$ V
POWER DISSIPATION (P_D):	
For $T_A = -40$ to $+70^\circ\text{C}$	250 mW
For $T_A = +70$ to $+85^\circ\text{C}$	150 mW
Above $+85^\circ\text{C}$	Derate Linearly at 6.5 mW/ $^\circ\text{C}$
DEVICE DISSIPATION PER OUTPUT TRANSISTOR:	
FOR $T_A = \text{FULL PACKAGE-TEMPERATURE RANGE}$	100 mW
OPERATING-TEMPERATURE RANGE (T_A)	-40 to $+85^\circ\text{C}$
STORAGE TEMPERATURE RANGE (T_{stg})	-65 to $+150^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance $1/16 \pm 1/32$ in. (1.59 ± 0.79 mm) from case for 10 s max.	$+265^\circ\text{C}$

STATIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C} \pm 5^\circ\text{C}$, $V_{DD} = 5.0$ V, $V_{SS} = 0$ V

CHARACTERISTIC		TEST CONDITIONS	LIMITS			UNITS
			Min.	Typ.	Max.	
Quiescent Device Current	I_{DD}	All inputs connected to V_{SS}	—	2.5	10	mA
Output Voltage Low Level	V_{OL}	All outputs, except 1.53 MHz Out at logic low. Output current, $I_{OL} = -200 \mu\text{A}$	—	—	0.4	V
Output Voltage High Level	V_{OH}	Output at logic high. Output current, $I_{OH} = +100 \mu\text{A}$	2.4	—	—	V
Video Input Threshold	V_{TH}	1.53 MHz In connected to V_{SS}	1.5	—	3.7	V
Input Low Voltage	V_{IL}	All inputs, except 1.53 MHz In and Video In	—	—	0.8	V
Input High Voltage	V_{IH}	All inputs, except 1.53 MHz In and Video In	3.9	—	—	V
Video Input Range - Positive Swing	V_P	1.53 MHz In connected to V_{SS} . Voltage higher than V_{TH} drives $+350 \mu\text{A}$ into input.	—	—	+1.0	V
Video Input Range - Negative Swing	V_N	1.53 MHz In connected to V_{SS} . Voltage lower than V_{TH} draws $-350 \mu\text{A}$ from input.	-1.0	—	—	V
Video Input Sensitivity High	V_{INH}	Voltage higher than V_{TH} for Bits Out goes low	—	—	+200	mV
Video Input Sensitivity Low	V_{INL}	Voltage lower than V_{TH} for Bits Out goes high	-200	—	—	mV
1.53-MHz Out Drive=Sink Current		Output at logic low with output current= $-100 \mu\text{A}$	—	—	0.6	V
1.53-MHz Out Drive=Source Current		Output at logic high with output Current= $+100 \mu\text{A}$	2.4	—	—	V
1.53-MHz In Capacitance		At V_{TH} level and 1.53-MHz In high	—	—	15	pF
Video In Capacitance		At V_{TH} level and 1.53-MHz In high	—	—	15	pF
1.53-MHz In Resistance		At V_{TH} level	30	—	—	K Ω
Video In Leakage Current	I_{IL}, I_{IH}	1.53-MHz In is high	—	—	± 1	μA

OPERATING CONDITIONS at T_A =Full Package Temperature Range. For maximum reliability, operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIMITS	UNITS
DC Operating-Voltage Range	4.5 - 5.5	V

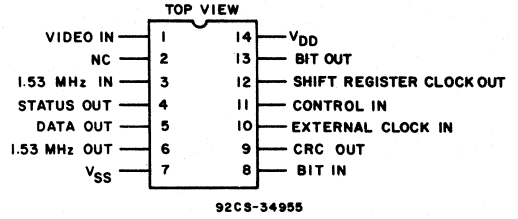


Fig. 2 - Terminal diagram.

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A=25^\circ\text{C}$; $C_L=50\text{ pF}$, Input $t_r, t_f=20\text{ ns}$, $V_{DD}=5\text{ V}$

CHARACTERISTIC		LIMITS			UNITS
		Min.	Typ.	Max.	
Propagation Delay Time:					
External Clock to Data Out (See Fig. 3)	T_{P1}	0.1	—	1	μs
Shift Register Clock to Data Out (See Fig. 4)	T_{P2}	50	—	400	ns
Control False to Status Out (See Fig. 3)	T_{P3}	—	—	1	μs
Delay Time:					
Status True to Control False (See Fig. 3)*	T_{D1}	1	—	—	μs
Control False to External Clock True (See Fig. 3)**	T_{D2}	1	—	—	μs
Video In Set Up Time (See Fig. 5)#	T_S	54.5	108.9	163.4	ns

*Applies to normal read conditions only.

**Determined by control system.

#1.53-MHz clock lags by $60^\circ \pm 30^\circ$.

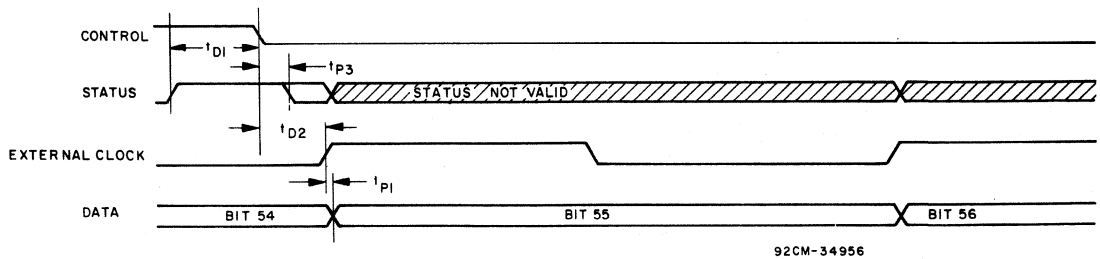


Fig. 3 - Typical sequence and data-timing diagram.

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CD3226E

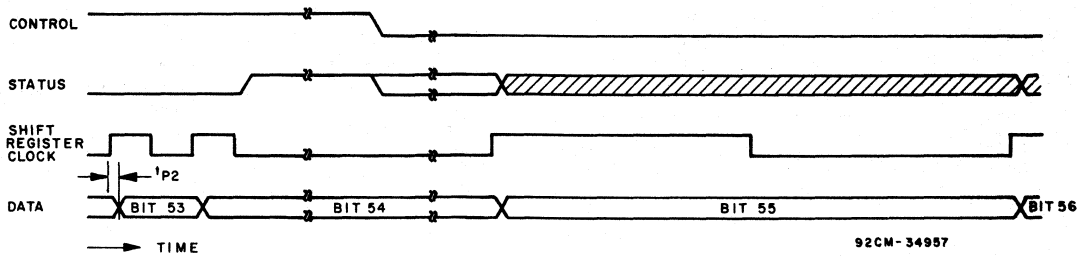


Fig. 4 - Shift register clock timing and typical sequence diagram.

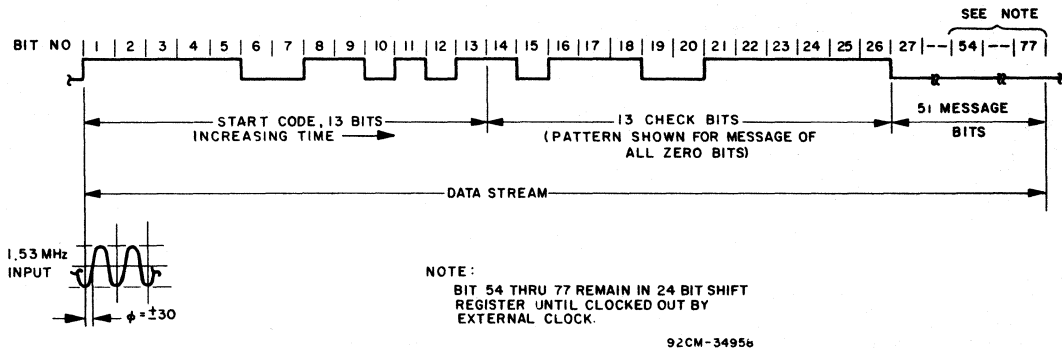
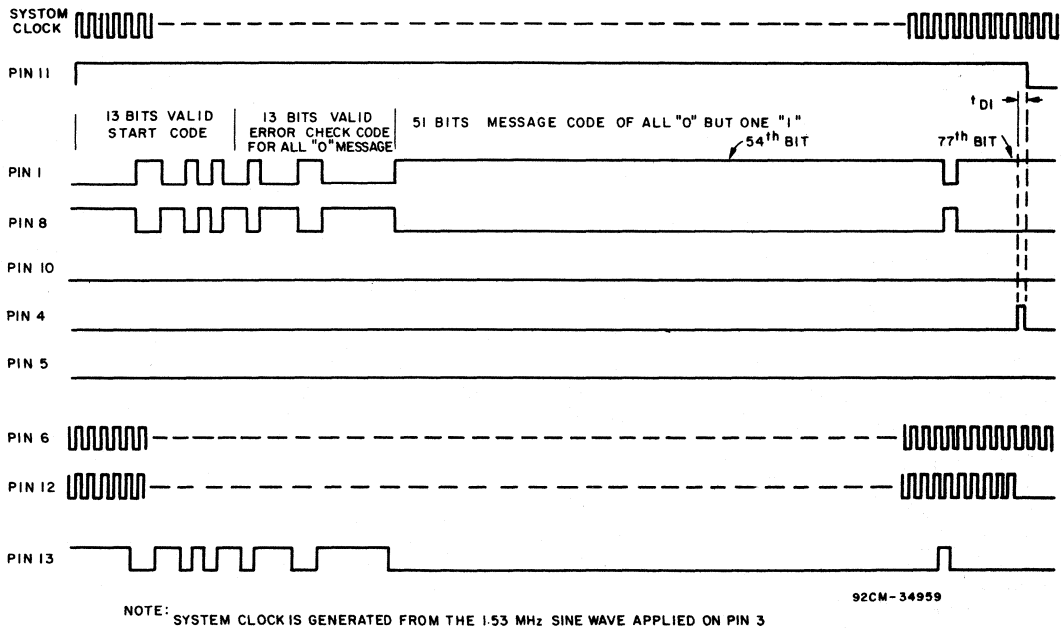


Fig. 5 - Code format, timing and phase diagram.



NOTE: SYSTEM CLOCK IS GENERATED FROM THE 1.53 MHz SINE WAVE APPLIED ON PIN 3

Fig. 6 - Functional timing diagram-invalid message code.

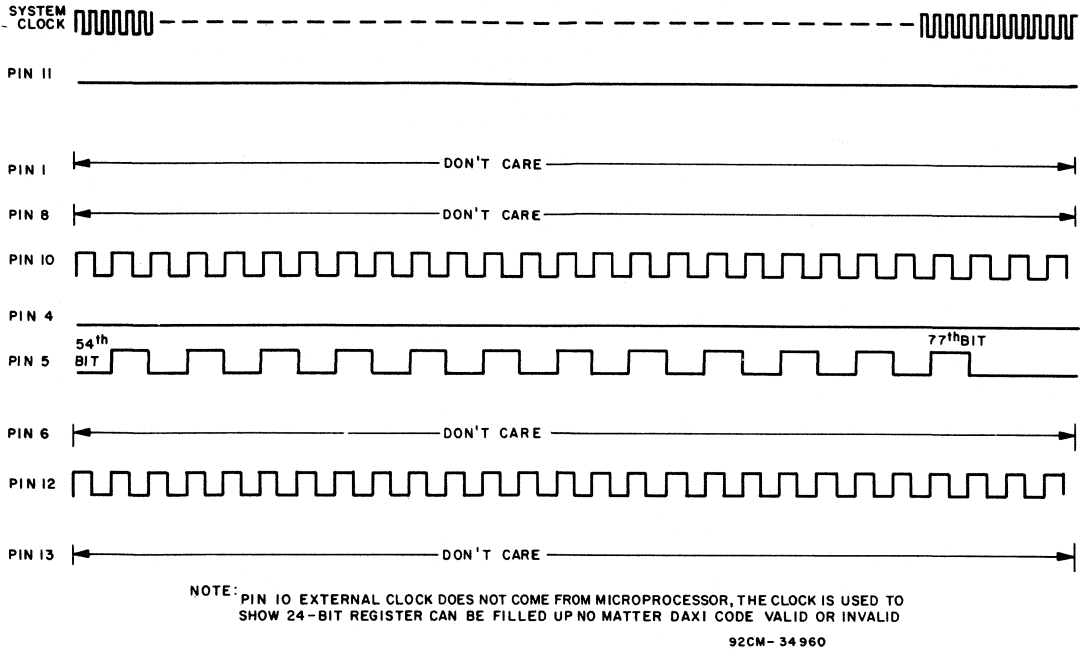


Fig. 7 - Functional timing diagram-shift registers function.

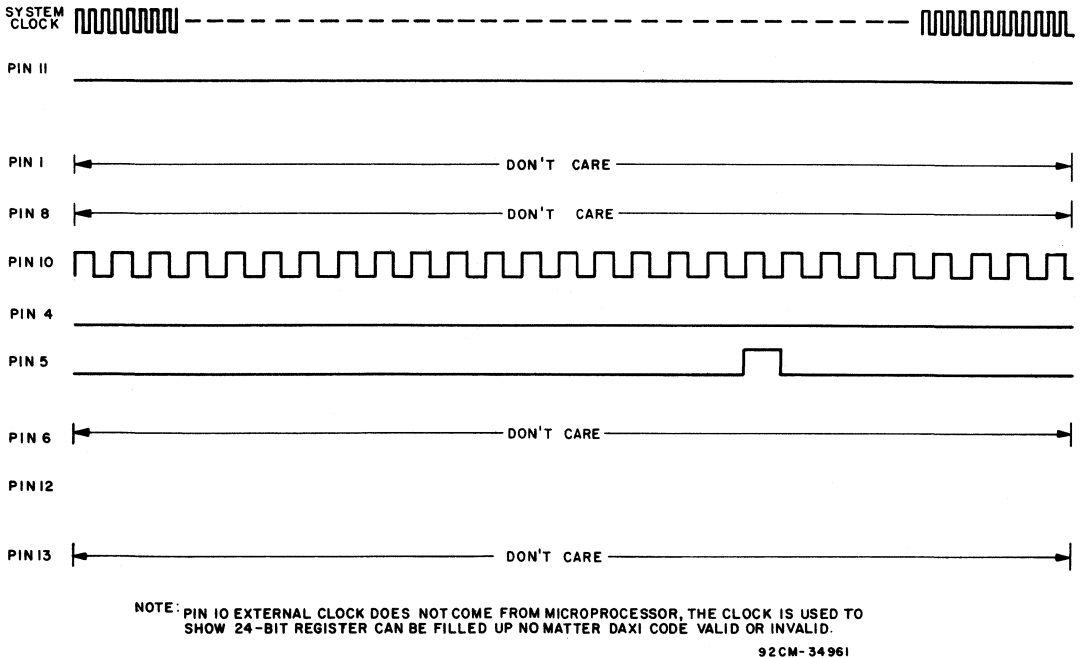
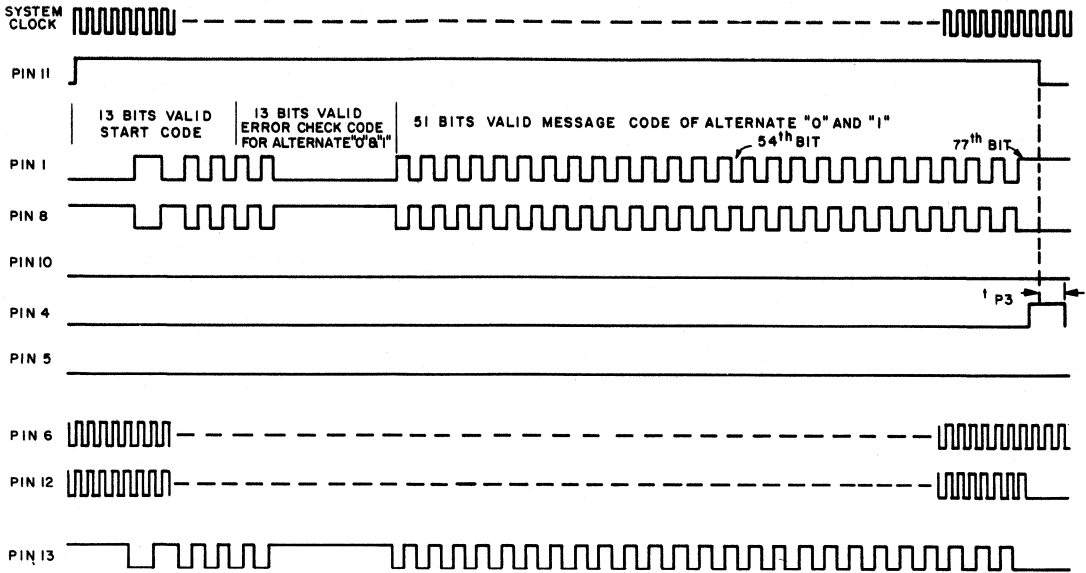


Fig. 8 - Functional timing diagram-valid DAXI code.

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CD3226E



92CM-34962

Fig. 9 - Functional timing diagram—shift registers function.

Audio Circuits

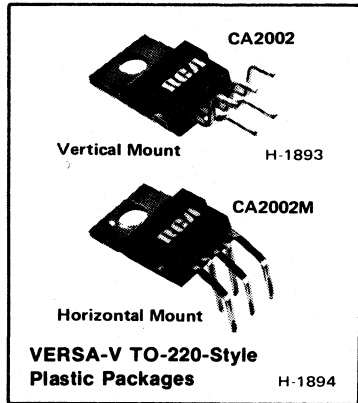
Technical Data

Drivers	Page
CA3094	See Page 213

Preamplifiers	
CA3036	See Page 402
CA3052	See Page 377

Power Amplifiers	
CA2002	1004
CA2004	1009

CA2002, CA2002M



8-Watt Audio Power Amplifier

Especially suited for automobile and other mobile applications

FEATURES:

- Output short-circuit and thermal overload protection
- Drives load impedance as low as 1.6Ω
- Load dump voltage surge protection
- Output current capability of up to 3.5A
- Few external components
- Versa-V power transistor package-requires no electrical insulation

The RCA-CA2002 is a monolithic silicon class B audio power amplifier designed for driving loads as low as 1.6Ω. It provides a high output current capability (up to 3.5A), very low harmonic and cross-over distortion, and load-dump voltage-surge protection.

The maximum operating supply-voltage of the CA2002 is 18 V, and internal protection is provided for peaks of up to 40 V, as shown in Fig. 18. Supply-voltage peaks of more than 40 V will require an LC network between the supply and terminal 5. An LC network, such as the one shown in Fig. 18, provides protection against supply-voltage surges of up to 120 V for 2 ms. This type of protection is ON when the supply voltage (pulsed or dc exceeds 18 V).

Thermal shut-down occurs if the output overloads (temporary or permanent), the ambient temperature is

excessive, or the junction temperature is excessive. None of these conditions results in device damage. They merely cause a temporary automatic reduction of output power and drain current, as shown in Figs. 16 and 17.

A heater fan motor run-down hysteresis circuit is included for automotive applications. Typical starting voltage is 10 volts; typical drop-out voltage is 6.5 volts.

The CA2002 is supplied in a 5-lead plastic TO-220-style VERSA-V package. All leads (except term. 3) are electrically insulated from the mounting flange, eliminating the need for insulating hardware. The VERSA-V package is available with two lead configurations. The CA2002 has a vertical-mount lead form, and the CA2002M has a horizontal-mount lead form.

MAXIMUM RATINGS, Absolute-Maximum Values:

PEAK SUPPLY VOLTAGE (50 ms)	40 V
DC SUPPLY VOLTAGE	28 V
OPERATING SUPPLY VOLTAGE	18 V
OUTPUT PEAK CURRENT:	
REPETITIVE	3.5 A
NON-REPETITIVE	4.5 A
POWER DISSIPATION, P _D at T _A = 90° C	15 W
THERMAL RESISTANCE, JUNCTION TO CASE	4° C/W
AMBIENT-TEMPERATURE RANGE:	
OPERATING	See Figures 16 & 17
STORAGE	-40 to +150° C
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 ± 1/32 inch (1.59 ± 0.79 mm)	
from case for 12 s max.	260° C

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V^+ = 14.4\text{ V}$
Unless otherwise specified (See Figure 2)

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS		
		Min.	Typ.	Max.			
Supply Voltage, V^+		11	—	18	V		
Quiescent Output Voltage, V_O	Measure at Term. 4	6.4	7.2	8	V		
Quiescent Drain Current, I_D	Measure at Term. 5	—	45	80	mA		
Output Power, P_O	THD = 10%, A = 40 dB, f = 1 KHz	$V^+ = 14.4\text{ V}$	$R_L = 4\ \Omega$	4.8	5.2	—	W
			$R_L = 2\ \Omega$	7	8	—	
		$V^+ = 16\text{ V}$	$R_L = 4\ \Omega$	—	6.5	—	
			$R_L = 2\ \Omega$	—	10	—	
Input Saturation Voltage, $V_I(\text{RMS})$		400	—	—	mV		
Input Sensitivity, e_i	A = 40 dB, f = 1 KHz	$P_O = 0.5\text{ W}$, $R_L = 4\ \Omega$	—	15	—	mV	
			$P_O = 0.5\text{ W}$, $R_L = 2\ \Omega$	—	11		—
		$P_O = 5.2\text{ W}$, $R_L = 4\ \Omega$	—	55	—		
			$P_O = 8\text{ W}$, $R_L = 2\ \Omega$	—	50		—
Frequency Response (–3 dB)	$R_L = 4\ \Omega$ (See Fig. 19)	25000			Hz		
Input Resistance, R_I (Term. 1)	f = 1 KHz	70	150	—	K Ω		
Open-Loop Voltage Gain, A_{OL}	$R_L = 4\ \Omega$, f = 1 KHz	—	80	—	dB		
Closed-Loop Voltage Gain, A	$R_L = 4\ \Omega$, f = 1 KHz	39.5	40	40.5	dB		
Input Noise Voltage, e_N	Freq. Resp. = 40 to 15,000 Hz (–3 dB)	400	4	—	μV		
Input Noise Current, i_N	Freq. Resp. = 40 to 15,000 Hz (–3 dB)	—	60	—	pA		
Efficiency; η	A = 40 dB, f = 1 KHz	$P_O = 5.2\text{ W}$, $R_L = 4\ \Omega$	—	68	—	%	
		$P_O = 8\text{ W}$, $R_L = 2\ \Omega$	—	58	—		
Power Supply Rejection Ratio, PSRR	$R_L = 4\ \Omega$, A = 40 dB, $R_g = 10\text{ K}\Omega$, $f_{\text{ripple}} = 100\text{ Hz}$, $V_{\text{ripple}} = 0.5\text{ V}$	30	35	—	dB		

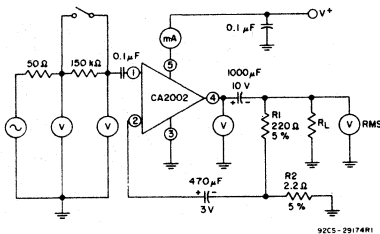


Fig. 1 – Test circuit.

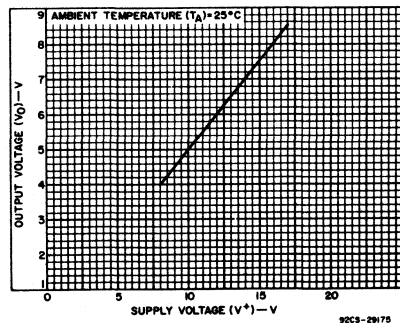


Fig. 2 – Typical quiescent output voltage as a function of supply voltage.

Linear Integrated Circuits

CA2002, CA2002M

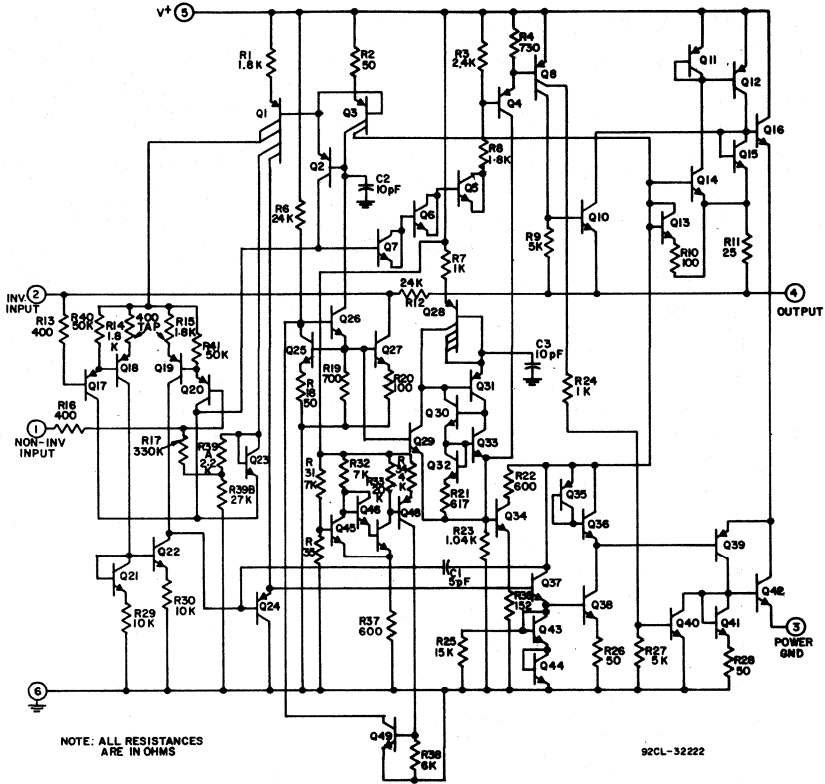


Fig. 3 - Schematic diagram.

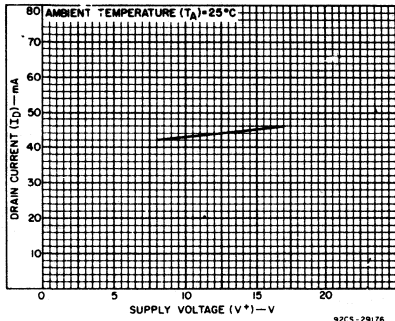


Fig. 4 - Typical quiescent drain current as a function of supply voltage.

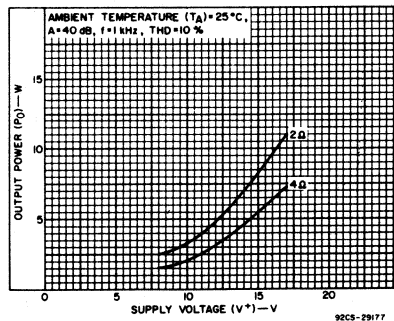


Fig. 5 - Typical output power as a function of supply voltage.

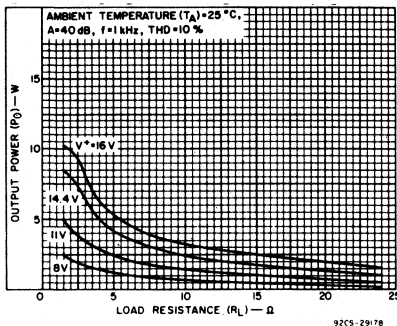


Fig. 6 - Typical output power as a function of load resistance.

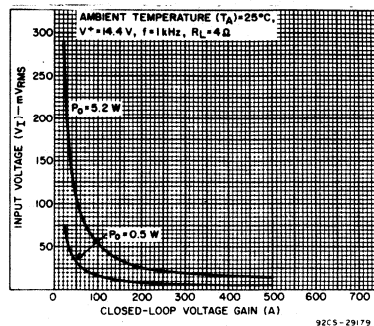


Fig. 7 - Typical input voltage as a function of closed-loop voltage gain.

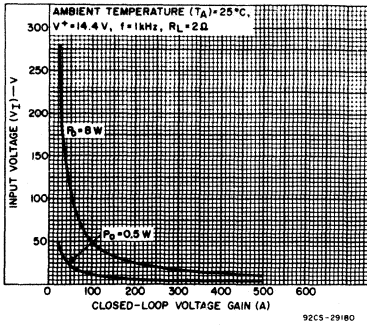


Fig. 8 — Typical input voltage as a function of closed-loop voltage gain.

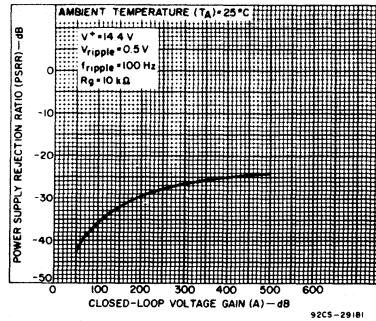


Fig. 9 — Typical power supply rejection ratio as a function of closed-loop voltage gain.

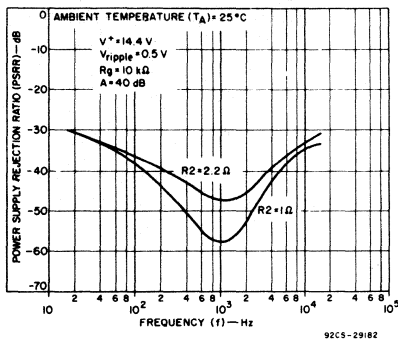


Fig. 10 — Typical power supply rejection ratio as a function of frequency.

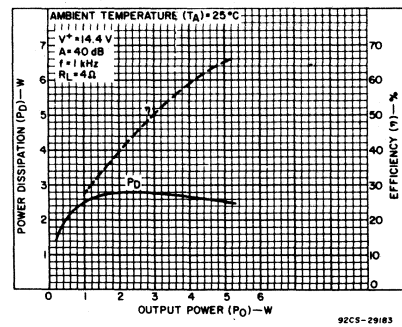


Fig. 11 — Typical power dissipation and efficiency as a function of output power.

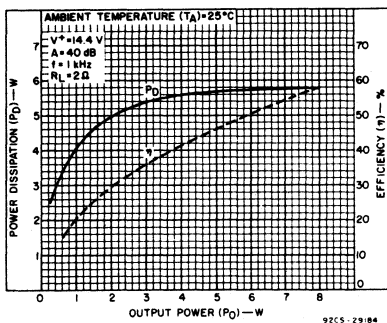


Fig. 12 — Typical power dissipation and efficiency as a function of output power.

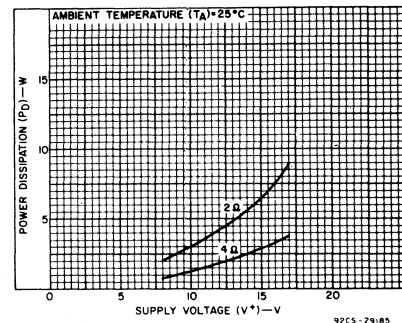


Fig. 13 — Maximum power dissipation as a function of supply voltage (sine-wave operation).

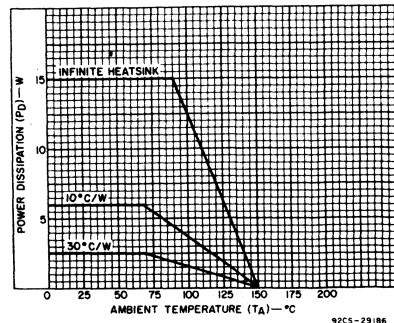


Fig. 14 — Maximum allowable power dissipation as a function of ambient temperature.

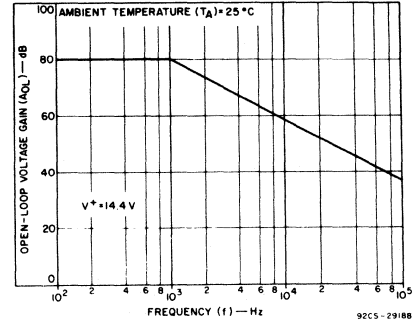


Fig. 15 — Open-loop voltage gain as a function of frequency.

Linear Integrated Circuits

CA2002, CA2002M

Load-Dump Voltage-Surge Protection

The maximum operating supply-voltage of the CA2002 is 18 V, and internal protection is provided for peaks of up to 40 V, as shown in Fig. 18. Supply-voltage peaks of more than 40 V will require an LC network between the supply and terminal 5. An LC network, such as the one shown in Fig. 18, provides protection against supply-voltage surges of up to 120 V for 2 ms. This type of protection is ON when the supply voltage (pulsed or

dc) exceeds 18 V.

Thermal Shut-Down

Thermal shut-down occurs if the output overloads (temporary or permanent), the ambient temperature is excessive, or the junction temperature is excessive. None of these conditions results in device damage. They merely cause a temporary automatic reduction of output power and drain current, as shown in Figs. 16 and 17.

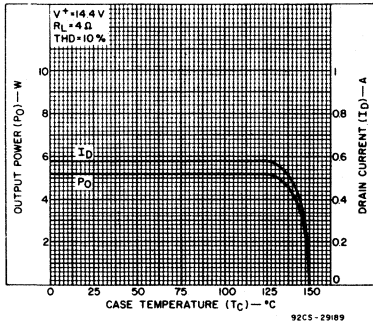


Fig. 16 — Output power and drain current as a function of case temperature.

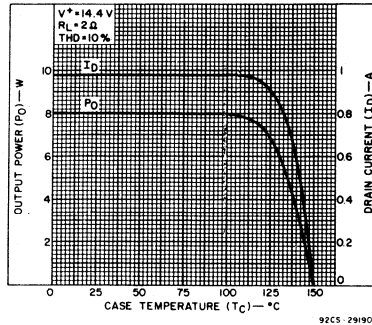


Fig. 17 — Output power and drain current as a function of case temperature.

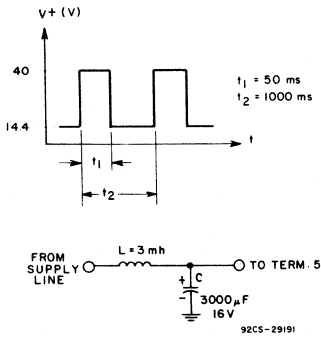


Fig. 18 — Supply-voltage surge protection network and timing diagram.

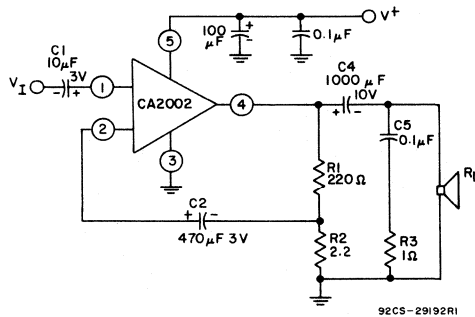


Fig. 19 — Typical application.

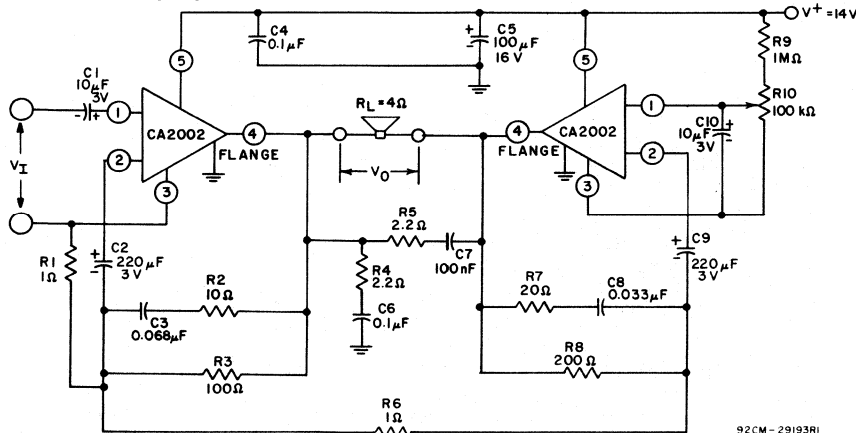
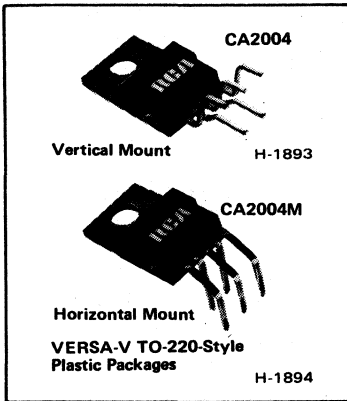


Fig. 20 — 15 W circuit-bridge application.

12-Watt Audio Power Amplifier

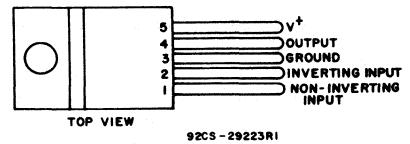


FEATURES:

- *VERSA-V 5-lead plastic TO-220-style package (insulation not required)*
- *Thermal overload protection*
- *Drives load impedance as low as 3.2Ω*
- *Deflection amplifier capability*
- *Output current capability of up to 3.5 A*
- *Few external components*

The RCA-CA2004 is a monolithic silicon class B audio power amplifier designed for driving loads as low as 3.2Ω. It provides a high output current capability (up to 3.5A), and very low harmonic and cross-over distortion.

The CA2004 is supplied in a 5-lead plastic TO-220-style VERSA-V package. All leads (except term. 3) are electrically insulated from the mounting flange, eliminating the need for insulating hardware. The VERSA-V package is available with two lead configurations. The CA2004 has a vertical-mount lead form, and the CA2004M has a horizontal-mount lead form.



TERMINAL ASSIGNMENT

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE	28 V
OPERATING SUPPLY VOLTAGE	26 V
OUTPUT PEAK CURRENT:	
REPETITIVE	3.5 A
NON-REPETITIVE	4.5 A
POWER DISSIPATION, P _D at T _A = 90°C	15 W
THERMAL RESISTANCE, JUNCTION TO CASE	4°C/W
AMBIENT-TEMPERATURE RANGE:	
OPERATING	0 to +125°C
STORAGE	-40 to +150°C
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 ± 1/32 inch (1.59 ± 0.79 mm) from case for 12 s max.	260°C

Linear Integrated Circuits

CA2004, CA2004M

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V^+ = 24\text{ V}$
 Unless otherwise specified (See Figure 1)

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS	
		Min.	Typ.	Max.		
Supply Voltage, V^+		8	—	26	V	
Quiescent Output Voltage, V_O	Measure at Term. 4	11	12	13	V	
Quiescent Drain Current, I_D	Measure at Term. 5	—	40	100	mA	
Output Power, P_O	THD = 10%, A = 40 dB, f = 1 KHz	$R_L = 4\ \Omega$	10	12	—	W
		$R_L = 8\ \Omega$	—	8	—	
Input Saturation Voltage, $V_{I(RMS)}$		400	—	—	mV	
Input Resistance, R_I (Term.1)	f = 1 KHz	70	150	—	K Ω	
Open-Loop Voltage Gain, A_{OL}	$R_L = 8\ \Omega$, f = 1 KHz	—	80	—	dB	
Closed-Loop Voltage Gain, A	$R_L = 8\ \Omega$, f = 1 KHz	39.5	40	40.5	dB	
Input Noise Voltage, e_N	Freq. Resp. = 40 to 15,000 Hz (–3 dB)	—	4	—	μV	
Power Supply Rejection Ratio, PSRR	$R_L = 4\ \Omega$, A = 40 dB, $R_g = 10\ \text{K}\Omega$, $f_{\text{ripple}} = 100\ \text{Hz}$, $V_{\text{ripple}} = 0.5\ \text{V}$	30	35	—	dB	

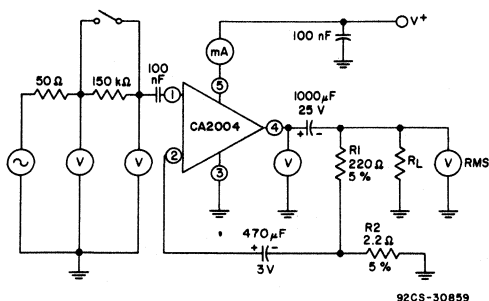


Fig. 1 – Test circuit.

Thermal Shut-Down:

Thermal shut-down occurs if the output overloads (temporary or permanent), the ambient temperature is excessive, or the junction temperature is excessive. None of these conditions results in device damage. They merely cause a temporary automatic reduction of output power and drain current.

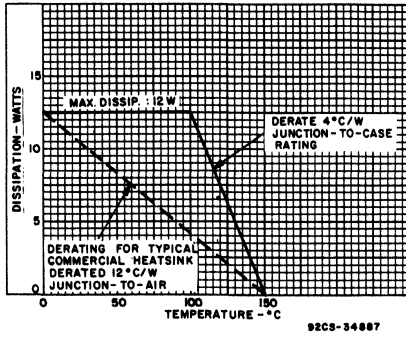


Fig. 2 — Derating curve

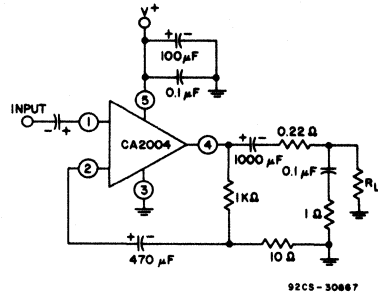


Fig. 3 — Typical application.

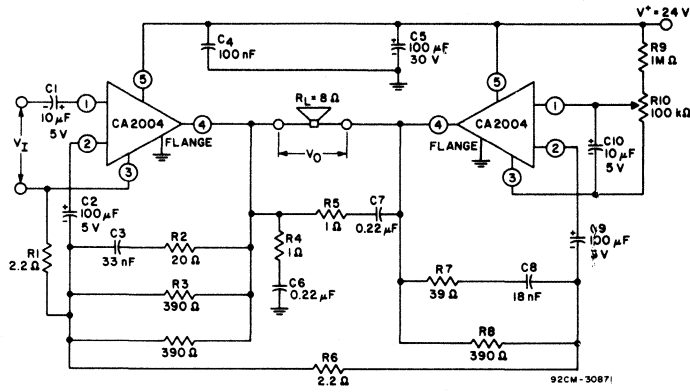


Fig. 4 — 25 W circuit-bridge application.

Radio Circuits Technical Data

AM/FM Communications Circuits

	Page
CA2111A	See Page 932
CA2136A	See Page 937
CA3011	See Page 939
CA3012	See Page 939
CA3013	See Page 945
CA3014	See Page 945
CA3075	1014
CA3076	1018
CA3088	1022
CA3089	1026
CA3123	1032
CA3179	See Page 630
CA3189	1036
CA3199	See Page 639
CA3209	1042

FM IF Circuits

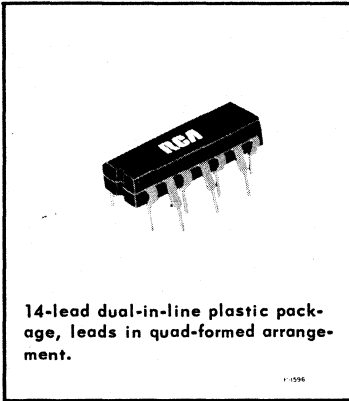
Gain Blocks

CA3011	See Page 939
CA3012	See Page 939
CA3076	1018

Subsystems

CA2111A	See Page 932
CA2136A	See Page 937
CA3013	See Page 945
CA3014	See Page 945
CA3075	1014
CA3089	1026
CA3189	1036
CA3209	1042

CA3075



FM IF Amplifier - Limiter, Detector, and Audio Preamplifier

For FM IF Amplifier Applications Up To 20 MHz In Communications Receivers And High-Fidelity Receivers

Features:

- Good sensitivity: Input limiting voltage (knee) = 250 μ V typ. at 10.7 MHz
- Excellent AM rejection: 55 dB typ. at 10.7 MHz
- Internal Zener diode regulation for the IF amplifier section
- Low harmonic distortion
- Differential peak detection: Permits simplified single-coil tuning
- Audio preamplifier voltage gain: 21 dB typ.
- Minimum number of external parts required

RCA CA3075 is an integrated circuit which provides, in a single monolithic chip, an FM IF subsystem for Communications and High-Fidelity Receivers. This device, shown in the schematic diagram (Fig. 2), consists of a multistage IF amplifier-limiter section with a Zener regulated power supply, an FM detector stage, and an AF preamplifier section. A typical application of the CA3075, in FM receiver circuits, is shown in the block diagram (Fig. 1).

The three-stage, emitter-follower-coupled IF amplifier section provides a 60-dB typ. voltage gain at an operating frequency of 10.7 MHz and features, because of its

transistor constant-current sink, an output stage with exceptionally good limiting characteristics.

The FM detector section, which utilizes a differential-peak-detection circuit, requires only a single coil in the associated outboard detector circuit; hence, tuning the detector circuit is a simple procedure.

The audio preamplifier circuit provides a 21-dB voltage gain with low impedance output for driving subsequent audio amplifier stages.

The CA3075 utilizes a 14-lead dual-in-line plastic package with leads in a special quad-formed arrangement.

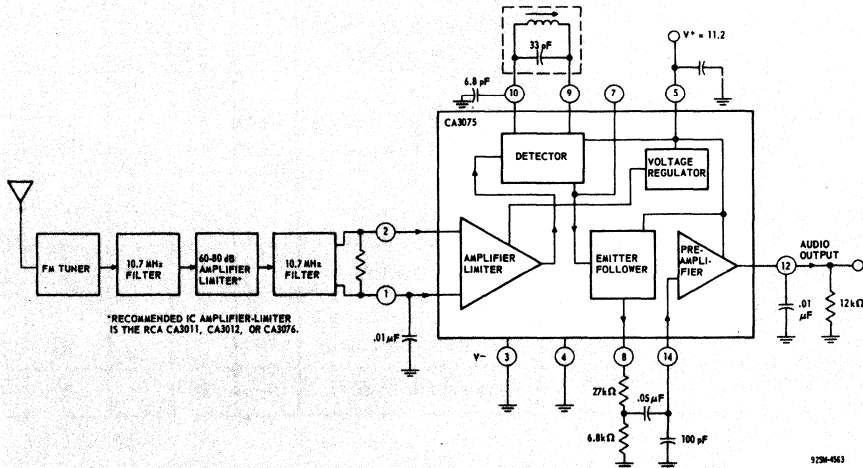


Fig. 1 - Block diagram of typical FM receiver utilizing the CA3075

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$

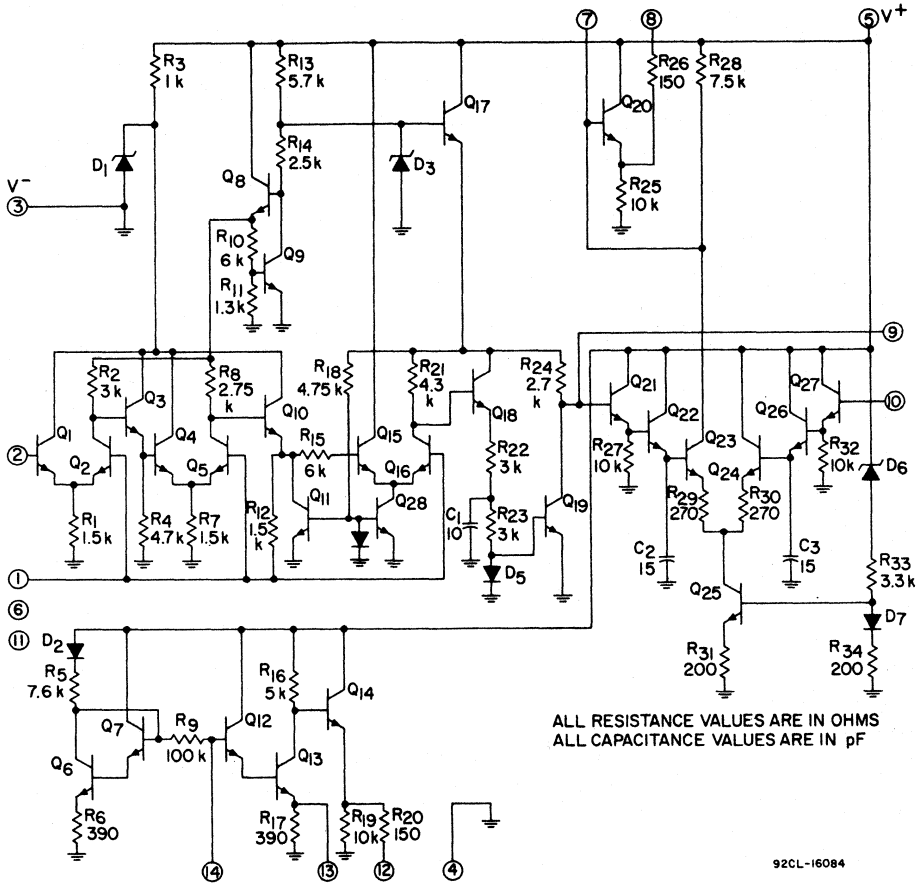
DC Supply Voltage [between Terminals 5 (V^+) and 3 (V^-)]	12.5	V
DC Current (into Terminal 5)	30	mA
Device Dissipation:		
Up to $T_A = 50^\circ\text{C}$	760	mW
Above $T_A = 50^\circ\text{C}$	derate linearly 7.6 mW/ $^\circ\text{C}$	
Ambient Temperature Range:		
Operating	- 40 to + 85	$^\circ\text{C}$
Storage	- 65 to + 150	$^\circ\text{C}$
Lead Temperature (During soldering for 10 s max.)	+ 260	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	LIMITS			UNITS	TEST CIRCUIT FIG. NO.
			MIN.	TYP.	MAX.		
Static Characteristics							
DC Voltage:							
At Terminal 7	V_7	$V^+ = 11.2\text{V}$	-	6.1	-	V	6
At Terminal 8	V_8		-	5.4	-	V	
At Terminal 12	V_{12}		-	5.2	-	V	
DC Current (into Terminal 5):							
At $V^+ = 8.5\text{V}$	I_5	-	8.5	15	-	mA	6
At $V^+ = 11.2\text{V}$			-	17.5	-	mA	
At $V^+ = 12.5\text{V}$			-	19	29	mA	
Dynamic Characteristics at $V^+ = 11.2$							
IF AMPLIFIER							
Input Limiting Voltage (knee, - 3 dB point)	$V_1(\text{lim})$	$f_0 = 10.7\text{ MHz}$ $f(\text{Modulation}) = 400\text{ Hz}$ Deviation = $\pm 75\text{ kHz}$	-	250	600	μV	3
AM Rejection	AMR	$f_0 = 10.7\text{ MHz}$ $f(\text{Modulation}) = 400\text{ Hz}$ FM: Deviation = $\pm 75\text{ kHz}$ AM: Modulation = 30%	-	55	-	dB	5
Input Impedance Components:							
Parallel Resistance	R_1	$f_0 = 10.7\text{ MHz}$	-	4.5	-	k Ω	-
Parallel Capacitance	C_1	$V_{IN} = 10\text{ mV RMS}$	-	4.5	-	pF	-
DETECTOR							
Recovered AF Voltage (at Terminal 12)	$V_0(\text{AF})$	$f_0 = 10.7\text{ MHz}$ $f(\text{Modulation}) = 400\text{ Hz}$	-	1.5	-	V	3
Total Harmonic Distortion	THD	Deviation = $\pm 75\text{ kHz}$	-	1	2	%	
AUDIO PREAMPLIFIER							
Voltage Gain	A(AF)	$V_{IN} = 100\text{ mV}$, $f_0 = 400\text{ Hz}$	-	21	-	dB	4
Total Harmonic Distortion	THD	$V_{OUT} = 2\text{ V}$, $f_0 = 400\text{ Hz}$	-	1.5	5	%	4

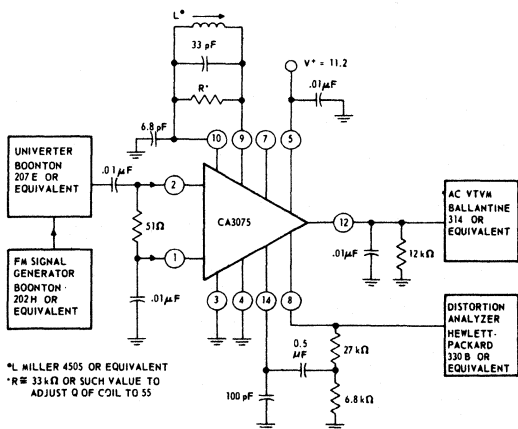
Linear Integrated Circuits

CA3075



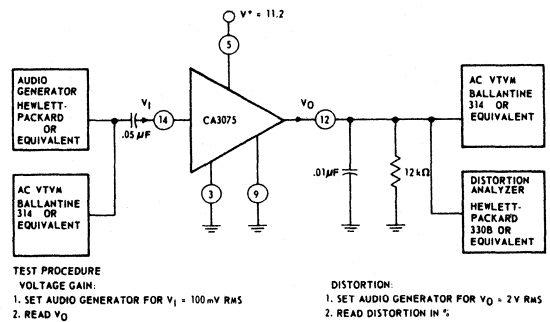
92CL-16084

Fig. 2 - Schematic diagram of CA3075



9755-45-5

Fig. 3 - Test circuit for input limiting voltage, recovered AF voltage, and total harmonic distortion



TEST PROCEDURE

VOLTAGE GAIN:

1. SET AUDIO GENERATOR FOR $V_i = 100\text{ mV RMS}$
2. READ V_o
3. GAIN = $20 \text{ LOG}_{10} V_o/V_i$

DISTORTION:

1. SET AUDIO GENERATOR FOR $V_o = 2\text{ V RMS}$
2. READ DISTORTION IN %

9755-156-1

Fig. 4 - Test circuit for audio preamplifier voltage gain and total harmonic distortion

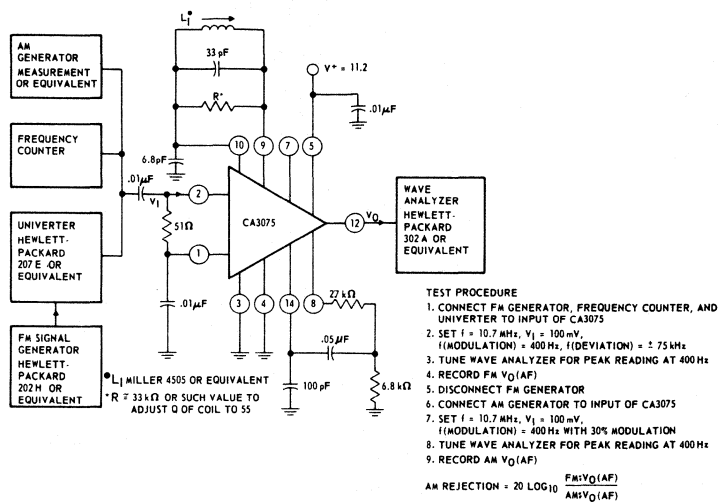


Fig. 5 - Test circuit for AM rejection

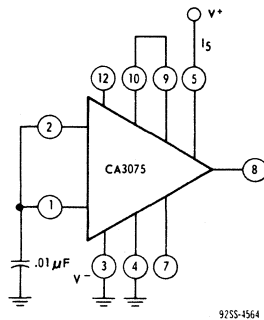
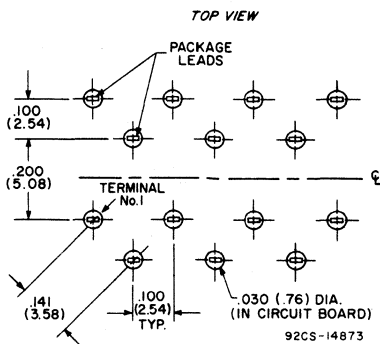


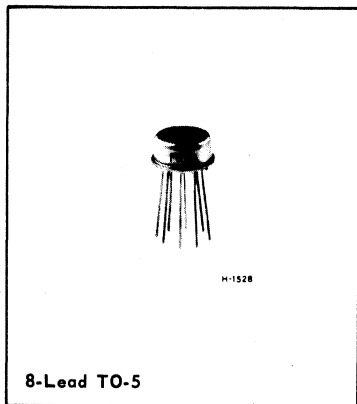
Fig. 6 - Test circuit for static characteristics

Recommended Mounting-Hole Dimensions and Spacings.



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated.

CA3076



High-Gain Wide-Band IF Amplifier-Limiter

For FM IF Amplifier Applications
in Communications Receivers

Features:

- exceptionally good sensitivity: input limiting voltage (knee) = $50 \mu\text{V}$ typ. at 10.7 MHz
- high gain: 80 dB with 2-kilohm load
- internal voltage supply regulator
- wide frequency capability: $> 20 \text{ MHz}$

RCA CA3076, monolithic integrated circuit, is a high-gain wide-band amplifier-limiter for use in the IF sections of Communications and High-Fidelity FM Receivers. The CA3076, shown in the schematic diagram (Fig. 2), consists of a four stage IF amplifier-limiter section with a voltage regulator section. A typical application of the CA3076 in FM receiver circuits is shown in the block diagram (Fig. 1).

The four-stage emitter-follower-coupled IF amplifier section provides an 80-dB voltage gain with a 2-kilohm load at a frequency of 10.7 MHz. The output stage has exceptionally good limiting characteristics because of its transistor constant-current sink. The voltage regulator section provides zener-regulated, decoupled voltages for the IF amplifier.

The CA3076 utilizes an hermetically-sealed 8-lead TO-5 package.

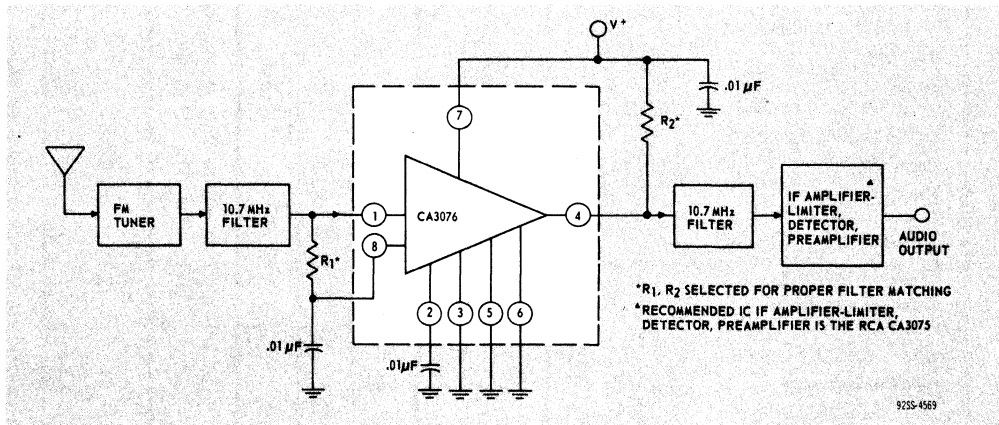


Fig. 1 - Block diagram of typical FM receiver utilizing the CA3076.

MAXIMUM RATINGS, Absolute Maximum-Values at $T_A = 25^\circ\text{C}$

DC Supply Voltage [between Terminals 7 (V^+) and 3 (V^-)]	15	V
DC Current (into Terminal 7).....	35	mA
Device Dissipation:		
Up to $T_A = 50^\circ\text{C}$	500	mW
Above $T_A = 50^\circ\text{C}$	derate linearly 5 mW/ $^\circ\text{C}$	
Ambient Temperature Range:		
Operating	- 55 to + 125	$^\circ\text{C}$
Storage	- 65 to + 150	$^\circ\text{C}$
Lead Temperature (During Soldering):		
At distance 1/32 in (3.17 mm) from seating plane for 10 s max.....	+ 260	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	LIMITS			UNITS	TEST CIRCUIT FIG. NO.
			MIN.	TYP.	MAX.		
Static Characteristics - $V^+ = 8.5\text{ V}$							
DC Current (into Term. 7)	I_7	-	10	15	24	mA	3
Quiescent Operating Current (into Term. 4)	I_4	-	-	0.65	-	mA	3
Dynamic Characteristics - $V^+ = 8.5\text{ V}$, $f_0 = 10.7\text{ MHz}$							
Input Limiting Voltage (knee, - 3dB point)	V_1 (lim.)	-	-	50	200	μV	-
Output Voltage	V_0	$V_1 = 20\mu\text{V}$	4	12	-	mV	5
Output Noise Voltage	V_N	$V_1 = 0$	-	1	-	mV	5
Forward Transfer Admittance: Magnitude Phase	$ Y_{21} $ θ_{21}	$V_1 = 10\mu\text{V}$	- -	6 80	- -	mho degrees	4
Reverse Transfer Admittance: Magnitude Phase	$ Y_{12} $ θ_{12}	-	- -	0.1 - 90	- -	μmho degrees	-
Input-Impedance Components: Parallel Resistance Parallel Capacitance	R_1 C_1	-	- -	7.5 4	- -	$\text{k}\Omega$ pF	-
Output-Impedance Components: Parallel Resistance Parallel Capacitance	R_0 C_0	-	50 -	- 1.7	- -	$\text{k}\Omega$ pF	-

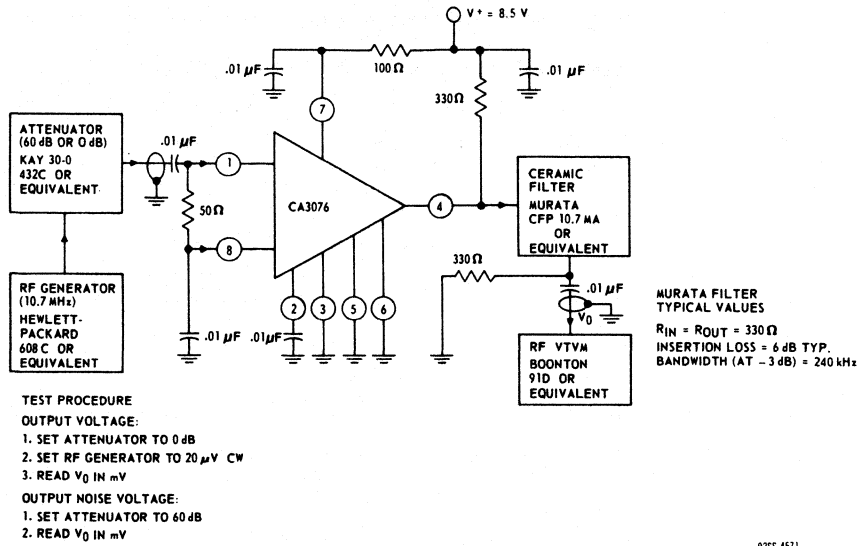
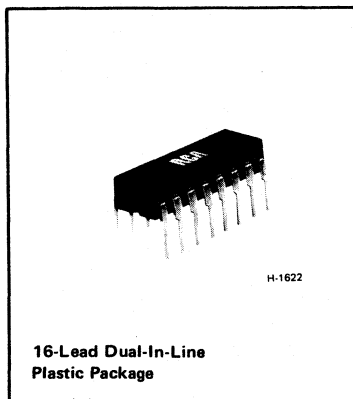


Fig. 5 - 10.7 MHz voltage gain and noise test circuit

CA3088E



AM Receiver Subsystem and General-Purpose Amplifier Array

Includes: AM Converter, IF Amplifiers, Detector and Audio Preamplifier
For Applications in a Variety of AM Broadcast and Communications Receivers and Applications Requiring an Array of Amplifiers

Features:

- Excellent overload characteristics
- AGC for IF amplifier
- Buffered output signal for tuning meter
- Internal Zener diode provides voltage regulation
- Two IF amplifier stages
- Low-noise converter and first IF amplifier
- Low harmonic distortion (THD)
- Delayed AGC for RF amplifier
- Terminals for optional inclusion of tone control

RCA-CA3088E*, a monolithic integrated circuit, is an AM subsystem that provides the converter, IF amplifier, detector, and audio preamplifier stages for an AM receiver.

The CA3088E also provides internal AGC for the first IF amplifier stage, delayed AGC for an optional external RF amplifier, a buffer stage to drive a tuning meter, and terminals facilitating the optional use of a tone control.

Fig. 2 is a functional diagram of the CA3088E. The signal from the low-noise converter is applied to the first IF amplifier and is then coupled to the second IF amplifier. This IF signal is then detected and externally filtered. The resultant audio signal is applied to an audio preamplifier. Optionally, a tone control circuit may be connected at the junction of the detector circuit and the audio preamplifier. The gain of the first IF amplifier stage is controlled by an internal AGC circuit. The CA3088E supplies a delayed AGC signal output for use with an external RF amplifier. A buffered output signal is also available for driving a tuning meter. A DC voltage, internally regulated by a Zener diode,

- Operates from wide range of power supplies: $V^+ = 6$ to 16 volts
- Optional AC and/or DC feedback on wide-band amplifier
- Array of amplifiers for general-purpose applications
- Suitable for use with optional external RF stage, either MOS or bipolar

supplies the second IF amplifier, the AGC and tuning meter circuits and may also be used with any other stage.

The CA3088E features four independent transistor amplifiers, each incorporating internal biasing for temperature tracking. These amplifiers are particularly useful in general-purpose amplifier, oscillator, and detector applications in a wide variety of equipment designs.

The CA3088E utilizes a 16-lead dual-in-line plastic package and operates over an ambient temperature range of -40°C to $+85^{\circ}\text{C}$.

*Formerly Developmental Type TA5842.

MAXIMUM RATINGS, Absolute Maximum Values, at $T_A = 25^{\circ}\text{C}$

DC SUPPLY VOLTAGE:		
Across Term. 5 and Terms. 3, 6, 13, 16, respectively	16	V
DC CURRENT:		
At Terms. 3, 6, 13, 16, respectively	10	mA
At Term. 10	30	mA
DEVICE DISSIPATION:		
Up to $T_A = 50^{\circ}\text{C}$	760	mW
Above $T_A = 50^{\circ}\text{C}$	derate linearly 7.6	mW/ $^{\circ}\text{C}$
AMBIENT TEMPERATURE RANGE:		
Operating	-40 to $+85$	$^{\circ}\text{C}$
Storage	-65 to $+150$	$^{\circ}\text{C}$
LEAD TEMPERATURE (During soldering):		
At distance not less than 1/32" (0.79 mm) from case for 10 seconds max.	+265	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS, at $T_A = 25^\circ\text{C}$, $V^+ = 12\text{ V}$.

CHARACTERISTIC	SYMBOL	TEST CONDITIONS		TYPICAL VALUES	UNITS	
			TEST CIRCUIT FIG. NO.			
Static (DC) Characteristics						
DC Voltages:						
Terms. 1, 4, 9, 11	$V_{1, 4, 9, 11}$		1	0.7	V	
Terms. 2, 7, 8	$V_{2, 7, 8}$			1.4	V	
Term. 10	V_{10}			5.6	V	
Term. 12	V_{12}			0	V	
Term. 15	V_{15}			3.5	V	
DC Current:						
Term. 3	I_3		1	0.35	mA	
Term. 6	I_6			1.0	mA	
Term. 10	I_{10}			20	mA	
Term. 13	I_{13}			0	mA	
Term. 16	I_{16}			1.2	mA	
Dynamic Characteristics						
Detector Output		30% Modulation	4	75	mV RMS	
Audio Amplifier Gain	AAF	$f = 1\text{ kHz}$	4	30	dB	
Audio Distortion		$V_{OUT} = 100\text{ mV}$	4	0.2	%	
Sensitivity:						
At Converter Stage Input		$f_{IN} = 1\text{ MHz}$ Signal-to-Noise Ratio (S/N) = 20 dB	2	200	$\mu\text{V/m}$	
At RF Stage Input			4	100	$\mu\text{V/m}$	
Total Harmonic Distortion	THD	30% Modulation	4	1.0	%	
Input Resistance:						
At Transistor Q1	R_{IN}	No AGC, Input signal frequency (f_{IN}) = 1 MHz		3500	Ω	
At Transistor Q5				2000	Ω	
Input Capacitance:						
At Transistor Q1	C_{IN}				17	pF
At Transistor Q5					12	pF
Feedback Capacitance:						
At Transistor Q1	C_{FB}			1.5	pF	
At Transistor Q5				1.5	pF	

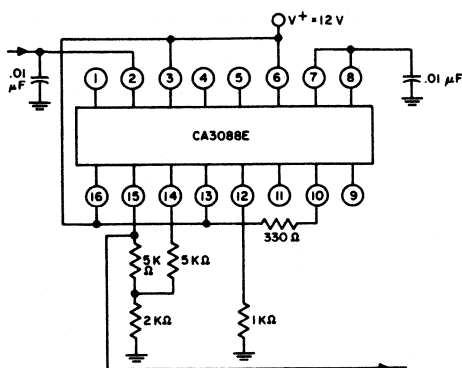


Fig.1—Test circuit for DC characteristics.

92CS-19068

Linear Integrated Circuits

CA3088E

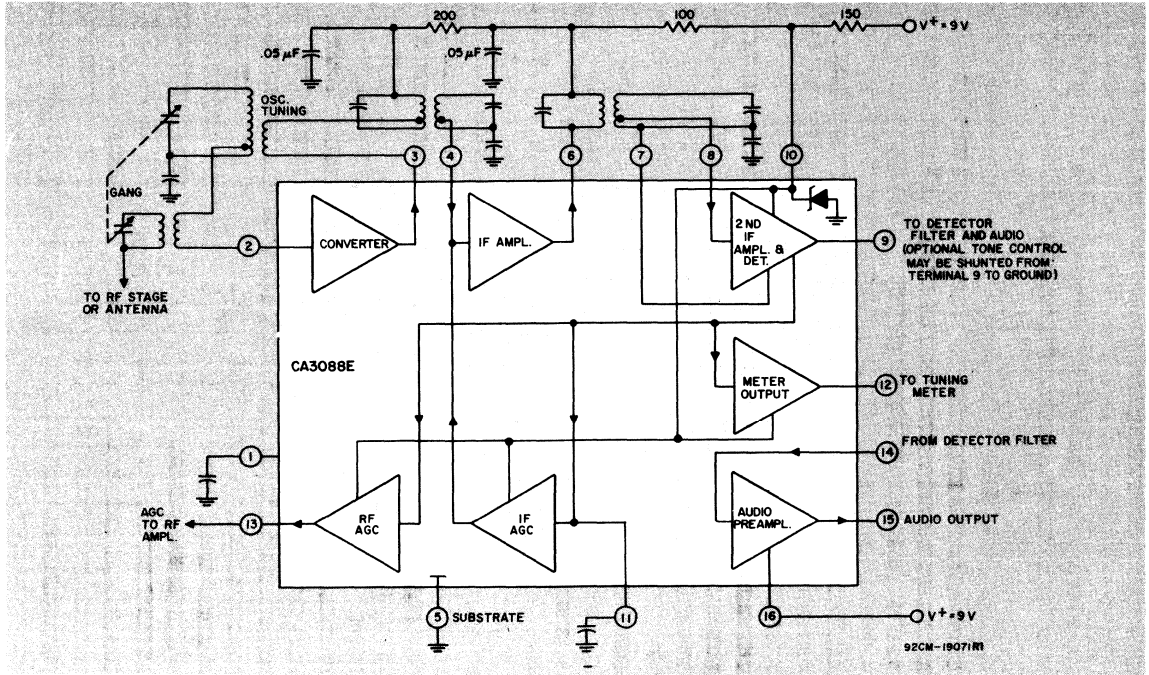


Fig.2—Functional block diagram of the CA3088E.

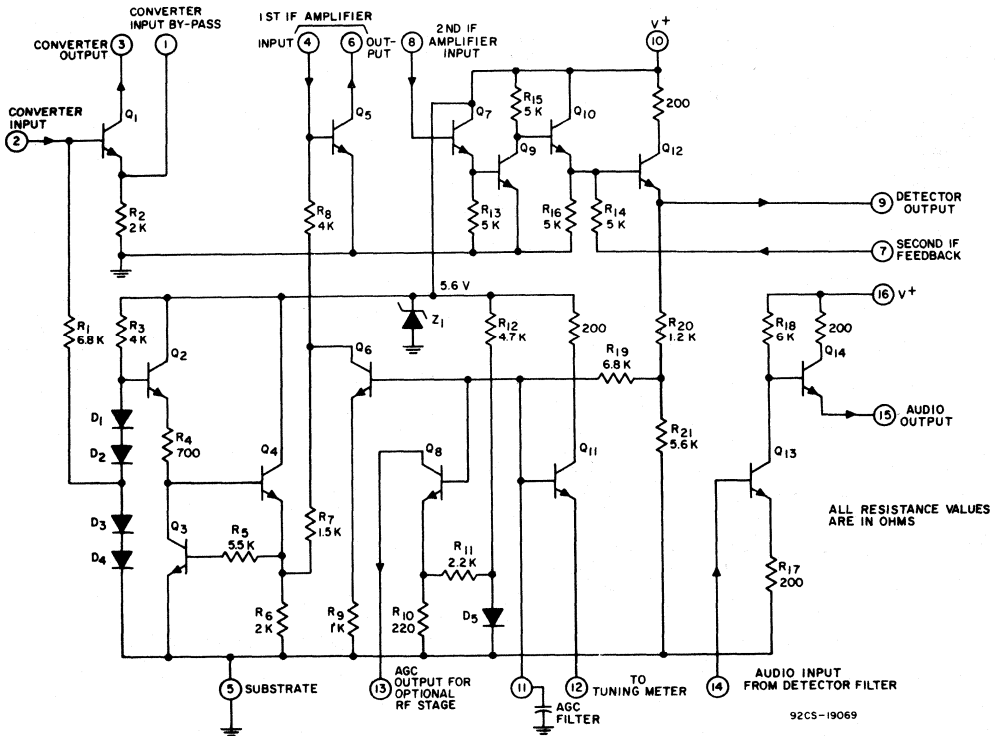
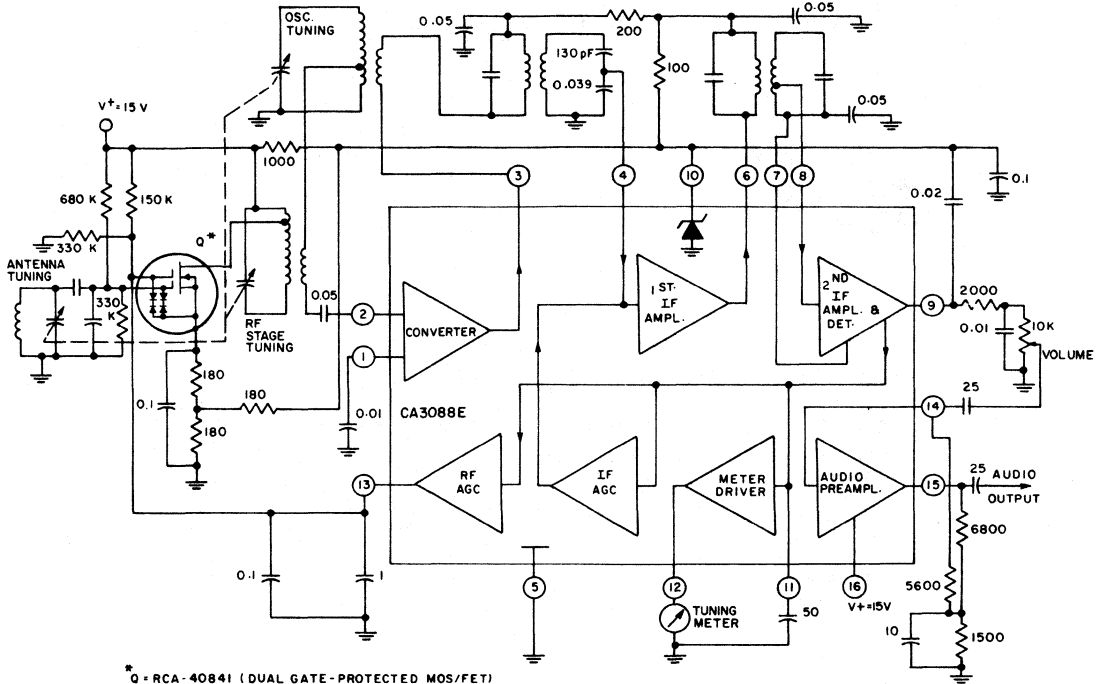


Fig.3—Schematic diagram of the CA3088E.

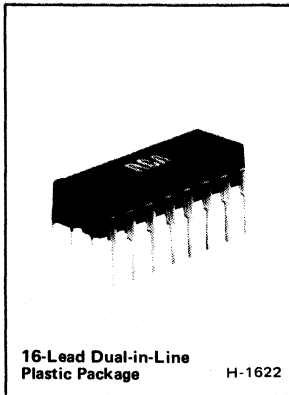


* Q - RCA-40841 (DUAL GATE-PROTECTED MOS/FET)
 ALL RESISTANCE VALUES ARE IN OHMS
 ALL CAPACITANCE VALUES ARE IN MICROFARADS

92CS-19065R1

Fig.4—Typical AM broadcast receiver using the CA3088E with optional RF amplifier stage.

CA3089E



FM IF System

For FM IF Amplifier Applications in High-Fidelity, Automotive, and Communications Receivers

Includes——IF Amplifier, Quadrature Detector, AF Preamplifier, and Specific Circuits for AGC, AFC, Muting (Squelch), and Tuning Meter

Features:

- Exceptional limiting sensitivity: 12 μ V typ. at -3 dB point
- Low distortion: 0.1% typ. (with double-tuned coil)
- Single-coil tuning capability
- High recovered audio: 400 mV typ.
- Provides specific signal for control of inter-channel muting (squelch)
- Provides specific signal for direct drive of a tuning meter
- Provides delayed AGC voltage for RF amplifier
- Provides a specific circuit for flexible AFC
- Internal supply-voltage regulators

RCA-CA3089E is a monolithic integrated circuit that provides all the functions of a comprehensive FM-IF system. Fig. 1 is a block diagram showing the CA3089E features, which include a three-stage FM-IF amplifier/limiter configuration with level detectors for each stage, a doubly-balanced quadrature FM detector and an audio amplifier that features the optional use of a muting (squelch) circuit.

The advanced circuit design of the IF system includes desirable deluxe features such as delayed AGC for the RF tuner, and AFC drive circuit, and an output signal to drive a tuning meter and/or provide stereo switching logic. In addition, internal power supply regulators maintain a nearly constant current drain over the voltage supply range of +8.5 to +16 volts.

The CA3089E is ideal for high-fidelity operation. Distortion in a CA3089E FM-IF System is primarily a function of the phase linearity characteristic of the outboard detector coil.

The CA3089E utilizes the 16-lead dual-in-line plastic package and can operate over the ambient temperature range of -40°C to +85°C.

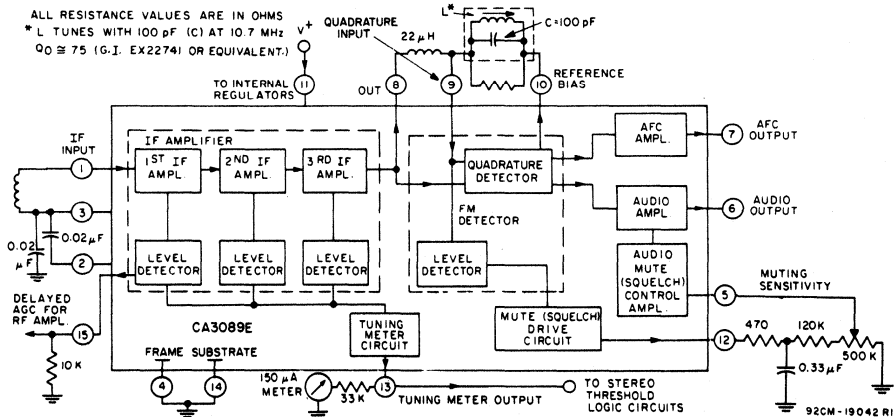


Fig. 1 - Block diagram of the CA3089E.

MAXIMUM RATINGS, Absolute Maximum Values

DC Supply Voltage:			
Between Terminals 11 and 4	16	V	
Between Terminals 11 and 14	16	V	
DC Current (out of Terminal 15)	2	mA	
Device Dissipation:			
Up to $T_A = 60^\circ\text{C}$	600	mW	
Above $T_A = 60^\circ\text{C}$	derate linearly	6.7	mW/ $^\circ\text{C}$
Ambient Temperature Range:			
Operating	-40 to +85	$^\circ\text{C}$	
Storage	-65 to +150	$^\circ\text{C}$	
Lead Temperature (During Soldering):			
At distance not less than 1/32" (0.79mm) from case for 10 seconds max.	+265	$^\circ\text{C}$	

ELECTRICAL CHARACTERISTICS, at $T_A = 25^\circ\text{C}$, $V_+ = 12$ Volts (See Figs. 5 and 6)

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS		
		Min.	Typ.	Max.			
Static (DC) Characteristics							
Quiescent Circuit Current	No signal input, Non muted	16	23	30	mA		
DC Voltages:							
Terminal 1 (IF Input)		1.2	1.9	2.4	V		
Terminal 2 (AC Return to Input)		1.2	1.9	2.4	V		
Terminal 3 (DC Bias to Input)		1.2	1.9	2.4	V		
Terminal 6 (Audio Output)		5.0	5.6	6.0	V		
Terminal 10 (DC Reference)	5.0	5.6	6.0	V			
Dynamic Characteristics							
Input Limiting Voltage (-3 dB point), V_1 (lim)	-	-	12	25	μV		
AM Rejection (Term. 6), AMR	$V_{IN} = 0.1\text{V}$, AM Mod. = 30%	45	55	-	dB		
Recovered AF Voltage (Term. 6) V_O (AF)	$V_{IN} = 0.1\text{V}$	$f_O = 10.7\text{ MHz}$	300	400	500	mV	
Total Harmonic Distortion, THD:* Single Tuned (Term. 6)			$f_{mod} = 400\text{ Hz}$	-	0.5	1.0	%
Double Tuned (Term. 6)				$\pm 75\text{ kHz}$	-	0.1	-
Signal plus Noise to Noise Ratio (Term. 6)		60	67	-	dB		

*THD characteristics are essentially a function of the phase characteristics of the network connected between terminals 8,9, and 10.

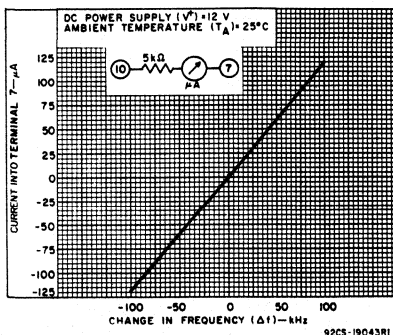


Fig. 2 — AFC characteristics (current at Term.7) as a function of change in frequency. (See test circuit Fig. 5.)

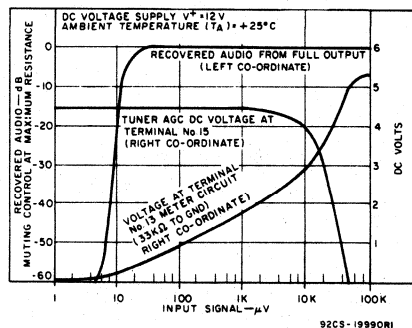


Fig. 3 — Muting action, tuner AGC, and tuning meter output as a function of input signal voltage. (See test circuit Fig. 5.)

Linear Integrated Circuits

CA3089E

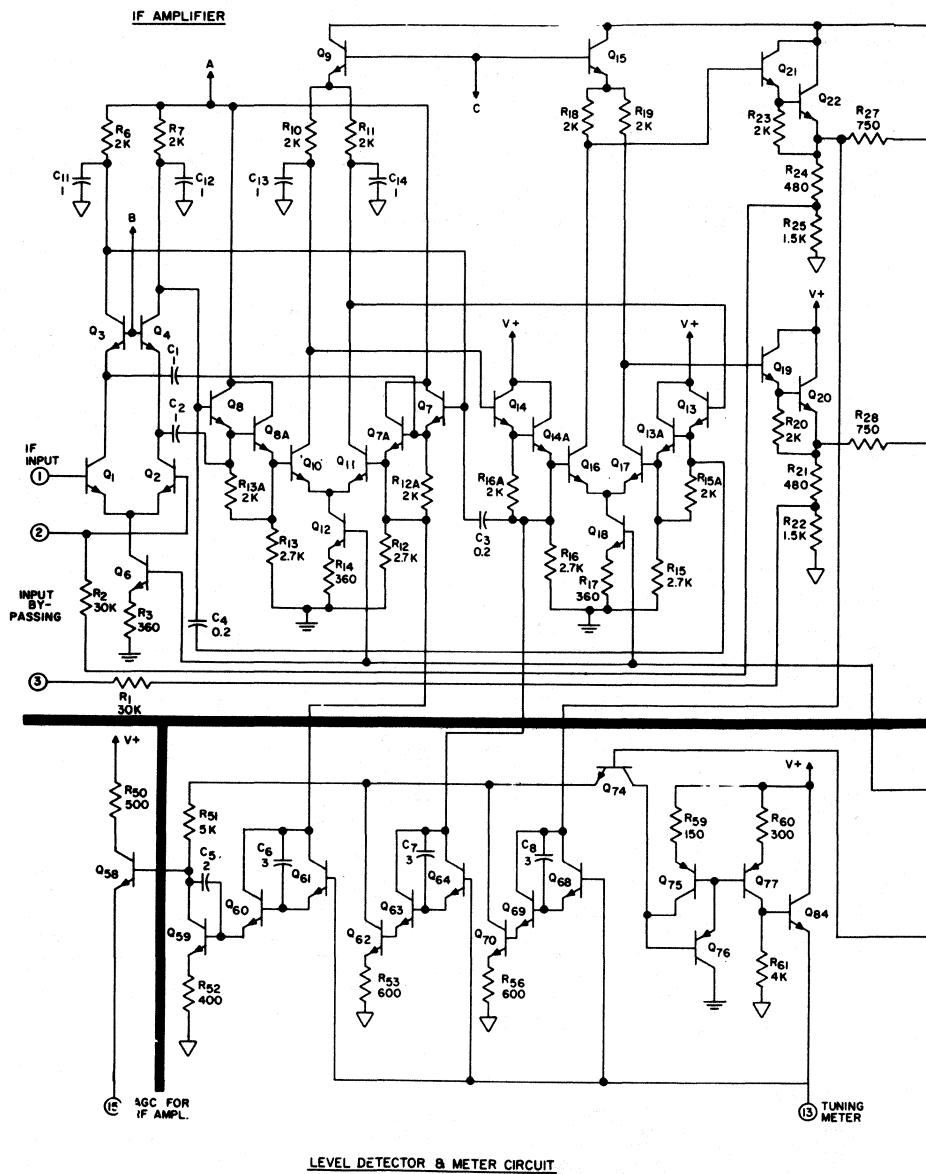


Fig. 4 - Schematic diagram of the CA3089E (cont'd on next page).

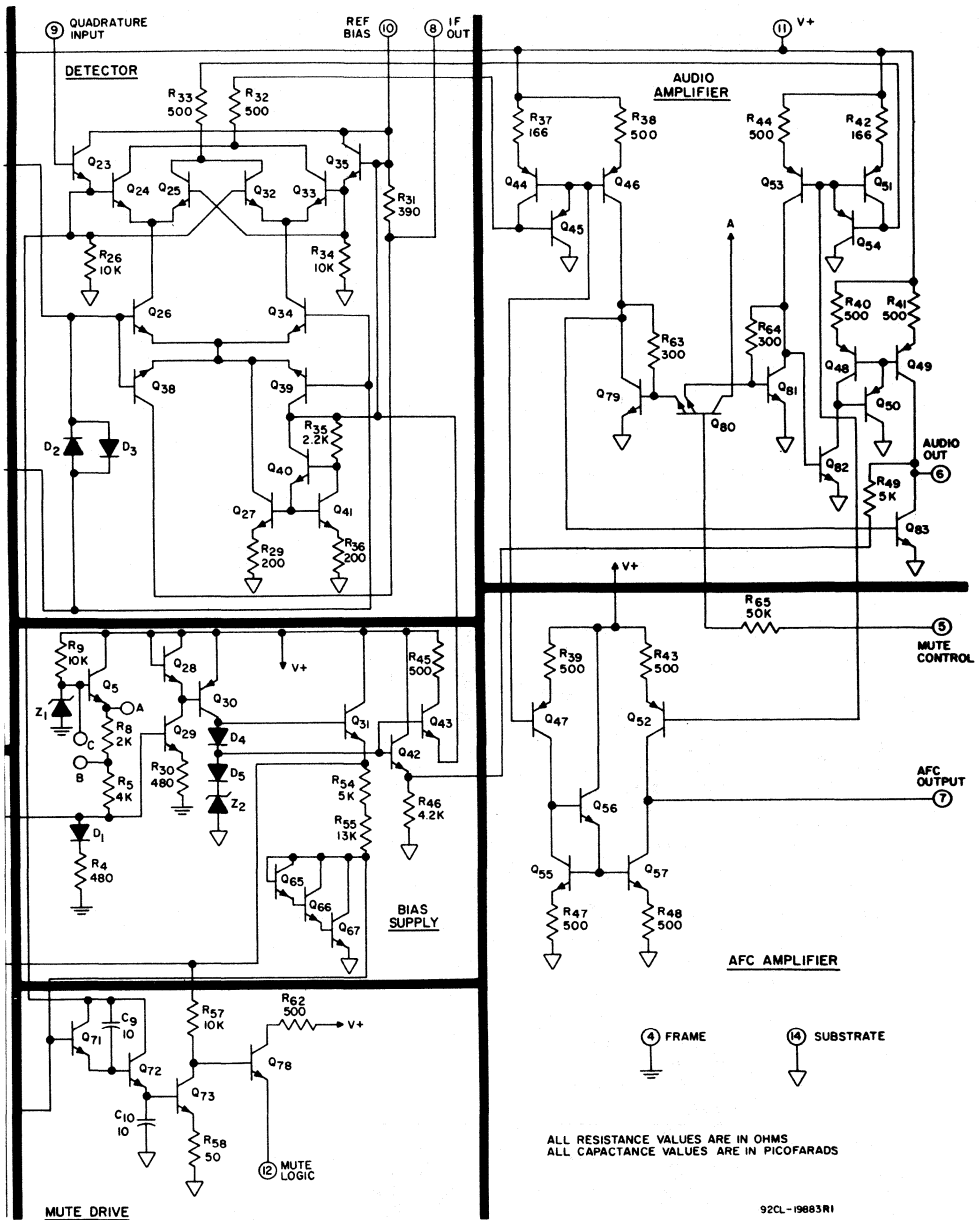


Fig. 4 - Schematic diagram of the CA3089E (cont'd from previous page).

Linear Integrated Circuits

CA3089E

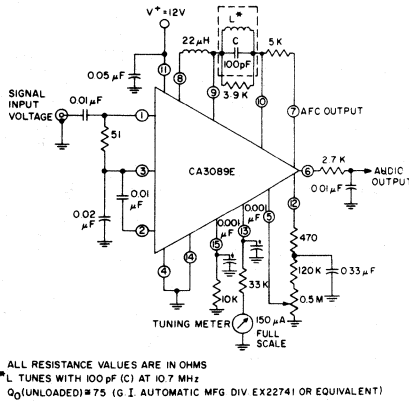


Fig. 5 — Test circuit for CA3089E using a single-tuned detector coil.

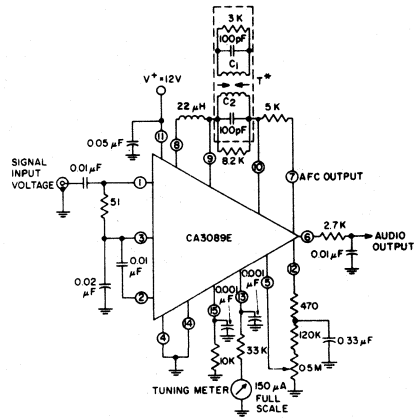


Fig. 6 — Test circuit for CA3089E using a double-tuned detector coil.

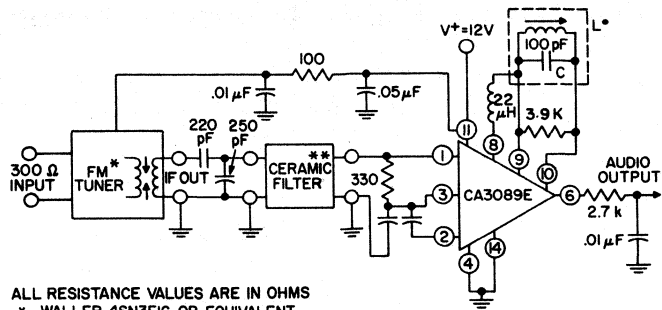


a) Bottom view of printed-circuit board.



b) Component side — top view.

Fig. 7 — Actual size photographs of the CA3089E and outboard components mounted on a printed-circuit board.



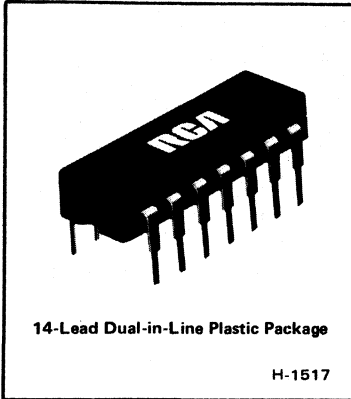
ALL RESISTANCE VALUES ARE IN OHMS
 * WALLER 4SN3FC OR EQUIVALENT
 ** MURATA SFG 10.7 MA OR EQUIVALENT
 • L TUNES WITH 100 pF (C) AT 10.7 MHz
 Q₀ UNLOADED *75 (G.I EX22741 OR EQUIVALENT)

92CS-19045

Performance data at $f_0 = 98$ MHz, $f_{MOD} = 400$ Hz,
 Deviation = ± 75 kHz:
 -3dB Limiting Sensitivity $2\mu V$ (Antenna Level)
 20dB Quieting Sensitivity $1\mu V$ (Antenna Level)
 30dB Quieting Sensitivity $1.5\mu V$ (Antenna Level)

Fig. 8 - Typical FM tuner using the CA3089E
 with a single-tuned detector coil.

CA3123E



14-Lead Dual-in-Line Plastic Package

H-1517

AM Radio Receiver Subsystem

Includes RF Amplifier, IF Amplifier, Mixer, Oscillator, AGC Detector, and Voltage Regulator

Features:

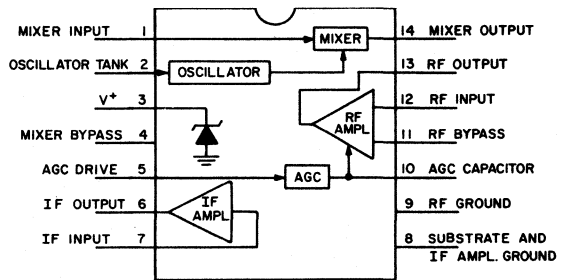
- Low-noise, low- R_b rf stage in cascode connection – eliminates Miller-Effect regeneration and allows controlled power rise by the choice of external components
- Mixer-oscillator stage with internal feedback – eliminates need for tapped or multi-winding oscillator coils
- Cascode if amplifier with controlled output impedance and negligible Miller Effect – eliminates regeneration and selectivity skewing
- Frequency-counter AGC circuit – allows control of AGC response by selection of the coupling capacitor
- Integral regulation with built-in surge protection
- Separately accessible amplifiers

The CA3123E* is a monolithic silicon integrated circuit that provides an rf amplifier, if amplifier, mixer, oscillator, AGC detector, and voltage regulator on a single chip. It is intended for use in super-heterodyne AM radio receiver applications particularly in automobiles. The CA3123E is supplied in a 14-lead dual-in-line plastic package and operates over the temperature range of -55° to 125°C .

* Formerly RCA Dev. No. TA6155

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE:	
At Terminal No. 3 (V^+)	9 V
At Terminal No. 6 (IF Output)	40 V
At Terminal No. 13 (RF Output)	20 V
At Terminal No. 14 (Mixer Output)	20 V
DC CURRENT:	
Into Terminal No. 3 (V^+)	35 mA
DEVICE DISSIPATION:	
Up to $T_A = 55^{\circ}\text{C}$	750 mW
Above $T_A = 55^{\circ}\text{C}$	derate linearly 6.67 mW/ $^{\circ}\text{C}$
AMBIENT TEMPERATURE RANGE:	
Operating	-55 to $+125^{\circ}\text{C}$
Storage	-65 to $+150^{\circ}\text{C}$
LEAD TEMPERATURE (During Soldering):	
At distance $1/16'' \pm 1/3''$ (1.59 mm \pm 0.79 mm)	
from case for 10 s max.	265 $^{\circ}\text{C}$



92CS-21666

Terminal assignment diagram.

ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	LIMITS			UNITS
			Min.	Typ.	Max.	
Static Characteristics In Circuit of Fig. 3						
DC Voltage:						
At Terminals 1, 4	V_1, V_4			4.7		V
At Terminals 2, 3, 14	V_2, V_3, V_{14}			6.8		V
At Terminal 5	V_5			0.25		V
At Terminal 6	V_6			12		V
At Terminal 7	V_7			0.76		V
At Terminals 8, 9	V_8, V_9			0		V
At Terminals 10, 11	V_{10}, V_{11}			0.71		V
At Terminal 12	V_{12}			0.71		V
At Terminal 13	V_{13}			4.0		V
DC Current:						
Into Terminals 1, 4, 5, 7, 8, 9, 10, 11, 12	$I_1, I_4, I_5, I_7, I_8, I_9, I_{10}, I_{11}, I_{12}$			0		mA
Into Terminal 2	I_2			1.2		mA
Into Terminal 3	I_3			15		mA
Into Terminal 6	I_6			4.3		mA
Into Terminal 13	I_{13}			4.5		mA
Into Terminal 14	I_{14}			0.170		mA
Performance Characteristics In Circuit of Fig. 3						
Sensitivity		Input Signal to Dummy Antenna at $f_{IN}=1$ MHz, 30% AM Modulation at $f_{MOD}=400$ Hz, for 11 mV output at V_O	—	2.3	5	μV
Signal-to-Noise Ratio	S/N	Ratio of Output at V_O with Modulation ON and then OFF, Input Signal=100 μV , 30% AM Modulation at $f_{MOD}=400$ Hz	34	43	—	dB
Overload Distortion		Input Signal set at 1 MHz, 90% AM Modulation, Distortion at V_O must be $\leq 10\%$	160000	400000	—	μV
Dynamic Characteristics For Indicated Stages In Circuit of Fig. 3						
Stage	Parallel Capacitance		Parallel Resistance		Transconductance	
	Input pF	Output pF	Input Ω	Output Ω	μmhos	
RF Amplifier	80	6	750	2×10^6 min.	140000	
IF Amplifier	35	3.5	950	10^4	80000	
Mixer	6	2	2000	2×10^6 min.	2500 (Mixer) 3000 (Amplifier)	

Linear Integrated Circuits

CA3123E

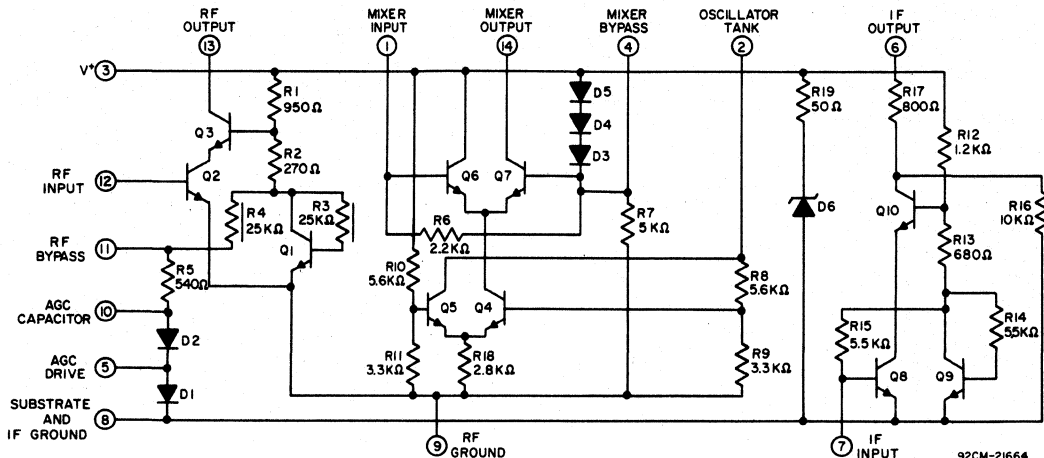
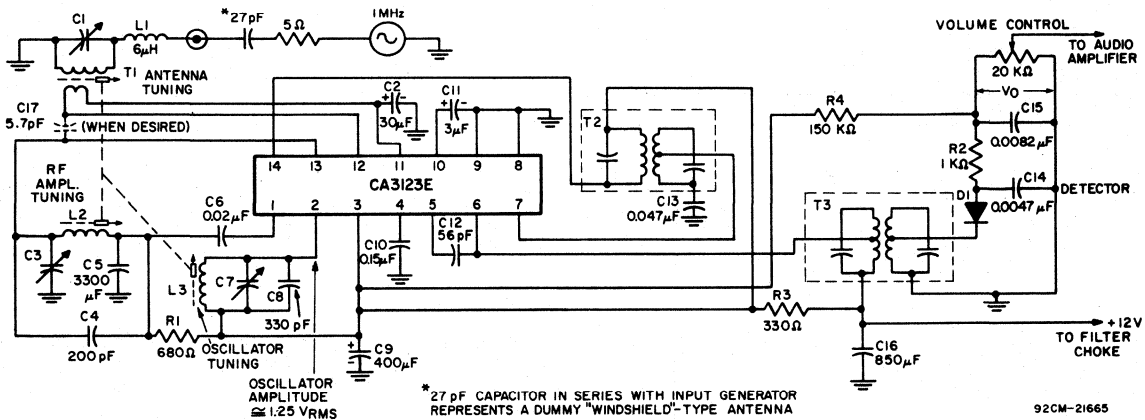


Fig. 2— Schematic diagram of CA3123E.



OSCILLATOR AMPLITUDE ≈ 1.25 VRMS

* 27 pF CAPACITOR IN SERIES WITH INPUT GENERATOR REPRESENTS A DUMMY 'WINDSHIELD'-TYPE ANTENNA

Transformer	Symbol	Frequency	Inductance μh (\approx)	Capacitance pF (\approx)	Q (\approx)	Total Turns To Tap Turns Ratio	Coupling
First IF:	T ₂	Primary	262 kHz	2840	60	none	critical
Secondary		$\approx 0.017 \approx 1/Q$					
Second IF:	T ₃	Primary	262 kHz	2840	60	8.5:1	—
Secondary		$\approx 0.017 \approx 1/Q$					
Antenna:	T ₁	Primary	1 MHz	195	65		
Secondary		Adjusted to an impedance of 75 Ω with primary resonant at 1 MHz. Coupling should be as tight as practical. Wire should be wound around end of coil away from tuning core.					
Coils	L ₁	7.9 MHz	6		50		
	L ₂	1 MHz	55		50		
	L ₃	1.262 MHz	41		40		

Fig. 3— Schematic diagram of AM radio receiver using CA3123E.

TYPICAL CHARACTERISTICS

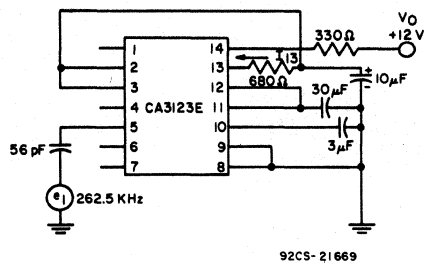
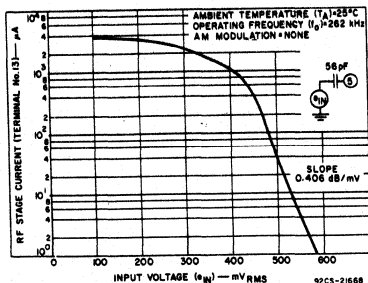


Fig. 4— Control of RF stage by signal into Terminal No. 5.

Fig. 5— Test circuit for Fig. 4.

PERFORMANCE CHARACTERISTICS IN CIRCUIT OF FIG. 3

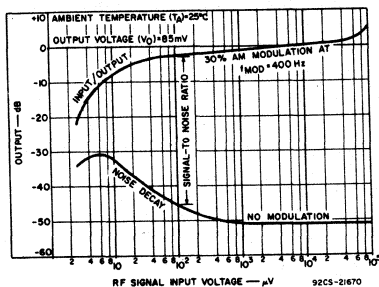


Fig. 6— Signal-to-noise performance.

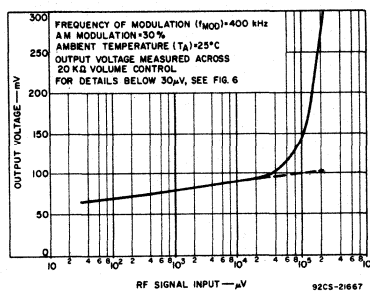


Fig. 7— AGC curve showing voltage rise (controlled by external capacitance of 5.7 pF: C_{17} , Fig. 3).

Change in slope in the vicinity of 40000 μ V signal input voltage is the result of the use of C_{17} (5.7 pF) in Fig. 3. The dotted curve indicates expected performance if $C_{17} = 0$.

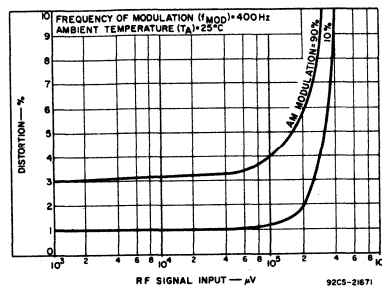
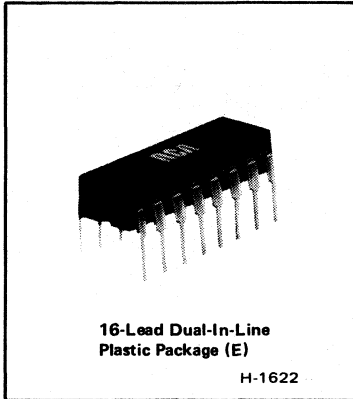


Fig. 8— Overload response.

CA3189E



FM IF System

Includes IF Amplifier, Quadrature Detector, AF Preamplifier, and Specific Circuits for AGC, AFC, Tuning Meter, Deviation-Noise Muting, and ON Channel Detector

For FM IF Amplifier Applications in High-Fidelity, Automotive, and Communications Receivers

Features:

- Exceptional limiting sensitivity: 12 μ V typ. at -3 dB point
- Low distortion: 0.1% typ. (with double-tuned coil)
- Single-coil tuning capability
- Improved S + N/N Ratio
- Externally programmable recovered audio level
- Provides specific signal for control of interchannel muting (squelch)
- Provides specific signal for direct drive of a tuning meter
- On channel step for search control
- Provides programmable AGC voltage for RF amplifier
- Provides a specific circuit for flexible audio output
- Internal supply-voltage regulators
- Externally programmable "on" channel step width, and deviation at which muting occurs

The RCA-CA3189E* is a monolithic integrated circuit that provides all the functions of a comprehensive FM-IF system. Fig. 1 shows a block diagram of the CA3189E, which includes a three-stage FM-IF amplifier/limiter configuration with level detectors for each stage, a doubly-balanced quadrature FM detector and an audio amplifier that features the optional use of a muting (squelch) circuit.

The advanced circuit design of the IF system includes desirable deluxe features such as programmable delayed AGC for the RF tuner, an AFC drive circuit, and an output signal to drive a tuning meter and/or provide stereo switching logic. In addition, internal power-supply regulators maintain a nearly constant current drain over the voltage supply range of +8.5 to +16 volts.

The CA3189E is ideal for high-fidelity operation. Distortion in a CA3189E FM-IF System is primarily a function of the phase linearity characteristic of the outboard detector coil.

The CA3189E has all the features of the CA3089E plus additions. See CA3189E features compared to the CA3089E in Table I.

The CA3189E utilizes the 16-lead dual-in-line plastic package and can operate over the ambient temperature range of -40°C to +85°C.

*Formerly Developmental Type No. TA10038.

MAXIMUM RATINGS, Absolute-Maximum Values at $T_A = 25^\circ\text{C}$:

DC SUPPLY VOLTAGE (between Terms. 11 and 4)	16 V
(between Terms. 11 and 14)	16 V
DC CURRENT (Out of Term. 15)2 mA
DEVICE DISSIPATION:	
Up to $T_A = 85^\circ\text{C}$	640 mW
Above $T_A = 85^\circ\text{C}$	derate linearly at 9.9 mW/ $^\circ\text{C}$
AMBIENT TEMPERATURE RANGE:	
Operating	-40 to +85 $^\circ\text{C}$
Storage	-65 to +150 $^\circ\text{C}$
LEAD TEMPERATURE (During soldering):	
At distance not less than 1/32 inch (0.79 mm) from case for 10s max.	+265 $^\circ\text{C}$

ELECTRICAL CHARACTERISTICS, at $T_A = 25^\circ\text{C}$, $V^+ = 12$ Volts

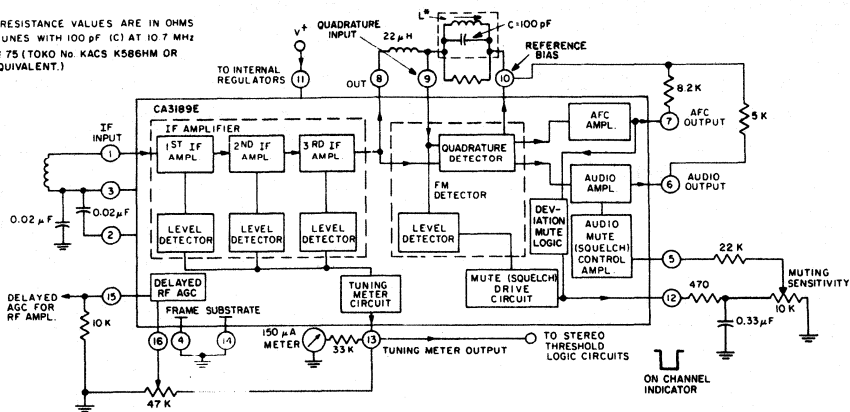
CHARACTERISTIC	SYMBOL	TEST CONDITIONS		LIMITS			UNITS	
			Circuit or Fig. No.	Min.	Typ.	Max.		
Static (DC) Characteristics								
Quiescent Circuit Current	I_{11}	No signal input, Non muted	3,4	20	31	40	mA	
DC Voltages: Terminal 1 (IF Input)	V_1			1.2	1.9	2.4	V	
Terminal 2 (AC Return to Input)	V_2			1.2	1.9	2.4	V	
Terminal 3 (DC Bias to Input)	V_3			1.2	1.9	2.4	V	
Terminal 15 (RF AGC)	V_{15}			7.5	9.5	11	V	
Terminal 10 (DC Reference)	V_{10}			5	5.6	6	V	
Dynamic Characteristics								
Input Limiting Voltage (-3 dB point)	$V_I(\text{lim})$	$V_{IN} = 0.1 \text{ V}$, AM Mod. = 30%	$f_O = 10.7 \text{ MHz}$,	3,4	-	12	25	μV
AM Rejection (Term. 6)	AMR				45	55	-	dB
Recovered AF Voltage (Term. 6)	$V_O(\text{AF})$				325	500	650	mV
Total Harmonic Distortion:* Single Tuned (Term. 6)	THD	$V_{IN} = 0.1 \text{ V}$	$f_{\text{mod.}} = 400 \text{ Hz}$,	3	-	0.5	1	%
Double Tuned (Term. 6)	THD				Deviation $\pm 75 \text{ kHz}$	4	-	0.1
Signal plus Noise to Noise Ratio (Term. 6)	S + N/N			3,4			65	72
Deviation Mute Frequency	$f_{\text{DEV.}}$		$f_{\text{mod.}} = 0$	3,6,7	-	± 40	-	kHz
RF AGC Threshold	V_{16}			3,4	-	1.25	-	V
On Channel Step	V_{12}	$V_{IN} = 0.1 \text{ V}$	$f_{\text{DEV.}} < \pm 40 \text{ kHz}$	3	-	0	-	V
			$f_{\text{DEV.}} > \pm 40 \text{ kHz}$		-	5.6	-	

*THD characteristics are essentially a function of the phase characteristics of the network connected between terminals 8, 9, and 10.

Linear Integrated Circuits

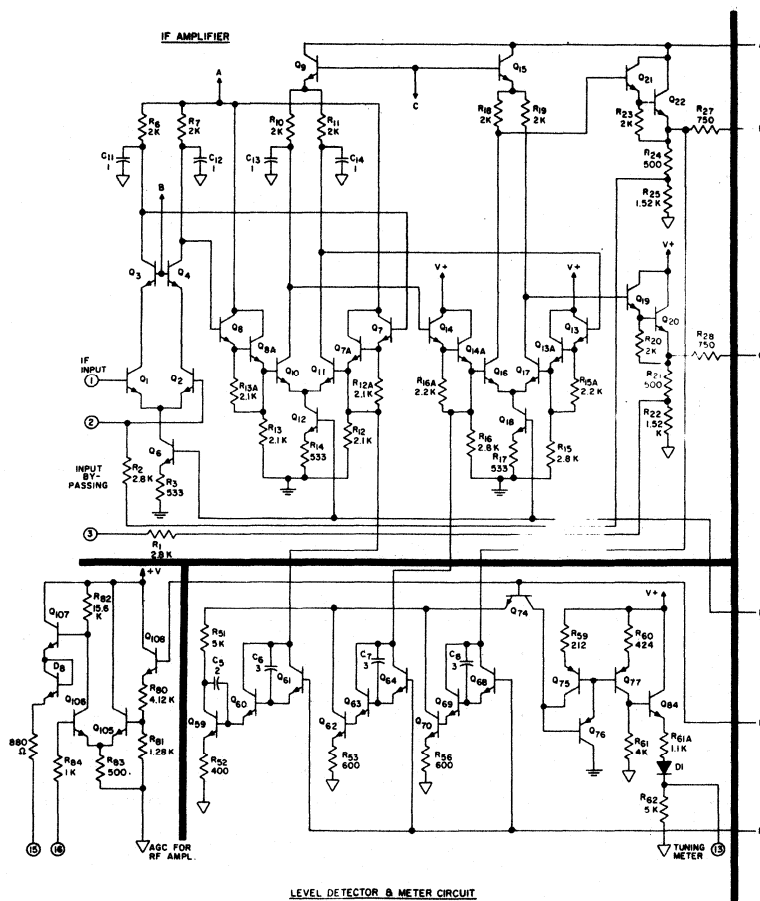
CA3189E

ALL RESISTANCE VALUES ARE IN OHMS
 * L TUNES WITH 100 pF (C1) AT 10.7 MHz
 $Q_0 \approx 75$ (TOKO No. KACS K586HM OR EQUIVALENT.)



92CM - 29951

Fig. 1 - Block diagram of the CA3189E.

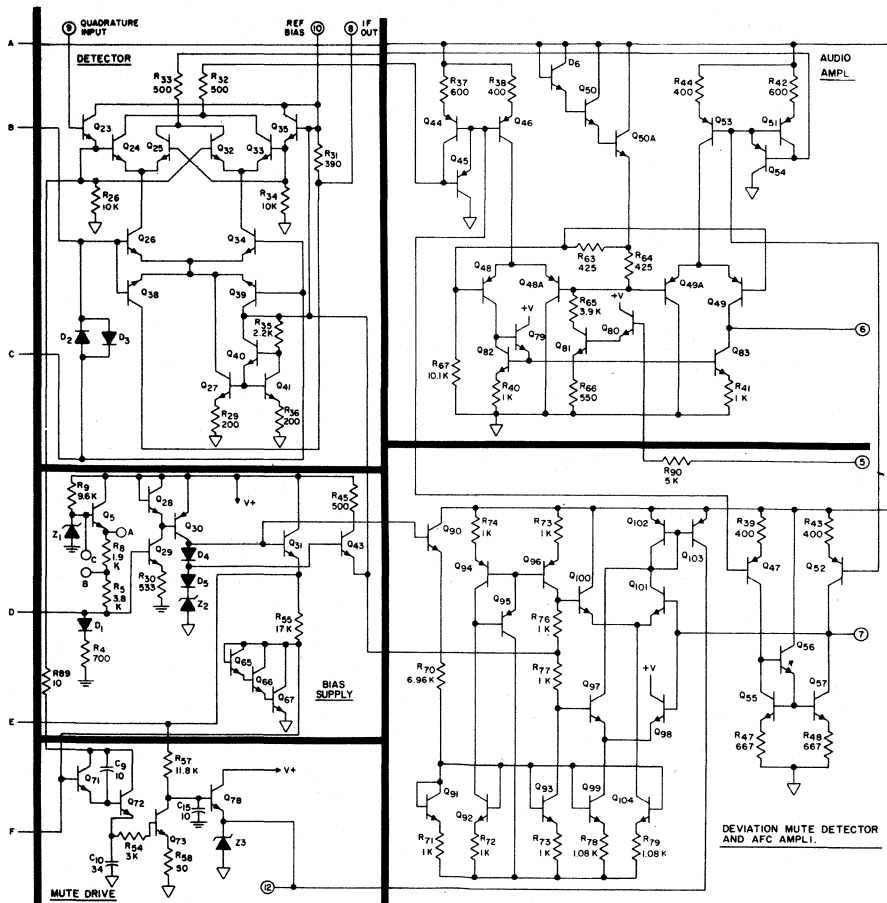


92CL - 29952

Fig. 2 - Schematic diagram of the CA3189E (cont'd on next page).

TABLE I - CA3189E Features Compared to CA3089E

FEATURES	CA3189E	CA3089E
Low Limiting Sensitivity (12 μ V typ.)	Yes	Yes
Low Distortion	Yes	Yes
Single-coil Tuning Capability	Yes	Yes
Programmable Audio Level	Yes	No
S/N Mute	Yes	Yes
Deviation Mute	Yes	No
Flexible AFC	Yes	Yes
Programmable AGC Threshold and Voltage	Yes	No
Typical S + N/N > 70 dB	Yes	No
Meter Drive Voltage Depressed at Very-Low Signal Levels	Yes	No
On-Channel Step Control Voltage	Yes	No



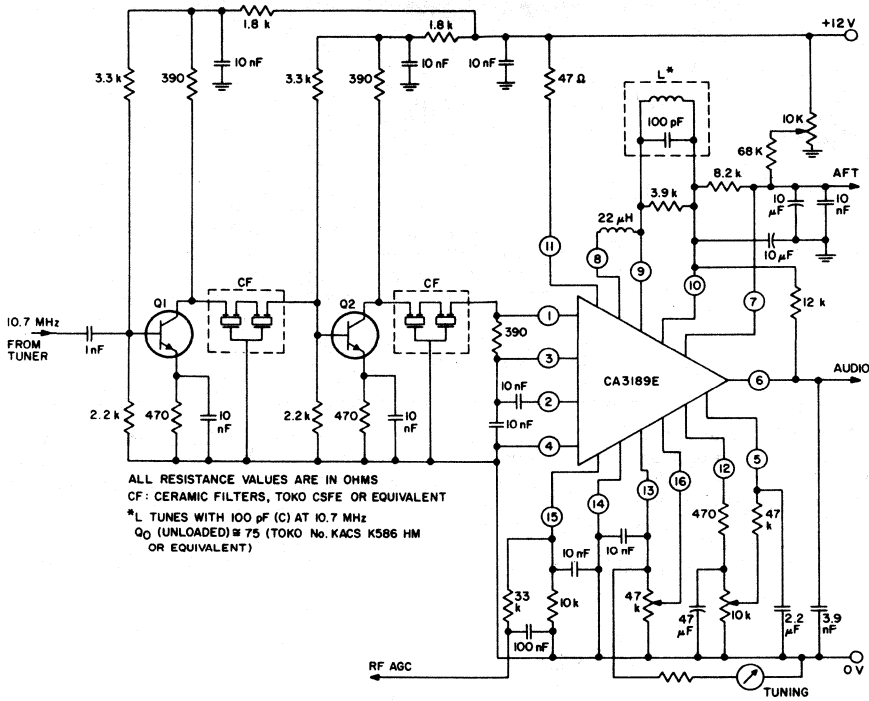
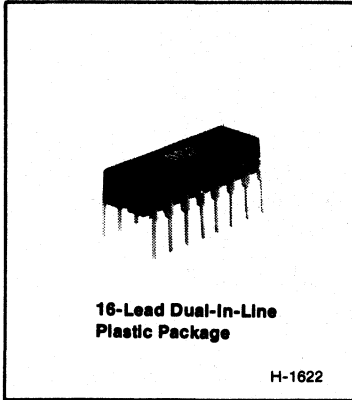


Fig. 9 — Complete FM IF system for high-quality receivers.

CA3209E



FM-IF System

For Search and Scan

Features:

- Exceptional limiting sensitivity: 12 μ V typ. at -3 dB point
- Exceptional temperature stability of tuning and stop-pulse window
- Single-coil tuning capability
- Externally programmable stop-pulse window width
- Programmable level for AGC action
- Forward AGC for pin-diode or bipolar rf amplifier
- Required input level to generate a stop-pulse is programmable

The RCA CA3209E[®] is a monolithic integrated circuit that provides all the functions of a comprehensive FM-IF system. It is intended for use in FM-IF amplifier applications in high-fidelity, automotive, and communications receivers where the synthesizer counter can be controlled by a stop-pulse for scan and search operation.

Fig. 1 shows the CA3209E features, which include a three-stage FM-IF amplifier/limiter configuration with level detectors for each stage, a doubly-balanced quadrature FM detector and an audio amplifier.

[®] Formerly Developmental Type No. TA10493B

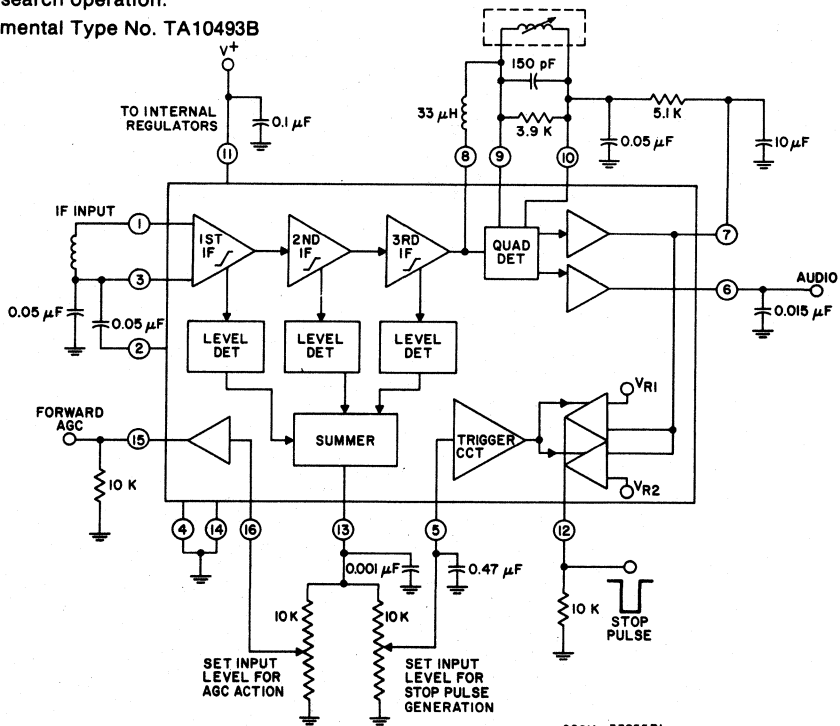


Fig. 1 - Block diagram of CA3290E.

CA3209E

The advanced circuit design of the IF system includes desirable deluxe features such as delayed AGC for the IF tuner, and an output signal to drive a tuning meter and/or provide stereo switching logic control of stop pulse and AGC thyristors. In addition, internal power supply regulators maintain a nearly constant current drain over the voltage supply range of +8.5 to +16 volts.

The CA3209E is ideal for high-fidelity operation. Distortion in a CA3209E FM-IF System is primarily a function of the phase linearity characteristic of the outboard detector coil.

The CA3209E utilizes the 16-lead dual-in-line plastic package and can operate over the ambient temperature range of -40°C to +85°C.

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY VOLTAGE:
 Between terminals 11 and 4 16 V
 Between terminals 11 and 14 16 V
 DC CURRENT (Out of Terminal 15) 2 mA
 DEVICE DISSIPATION:
 Up to $T_A = 85^\circ\text{C}$ 735 mW
 Above $T_A = 85^\circ\text{C}$ Derate linearly 11.4 mW/ $^\circ\text{C}$
 AMBIENT TEMPERATURE RANGE:
 Operating -40 to +85°C
 Storage -65 to +150°C
 LEAD TEMPERATURE (During Soldering):
 At distance not less than 1/32" (0.79 mm) from case for 10 seconds max. +265°C

**ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$, $V_+ = 12\text{ Volts}$
 (See Fig. 3 for Test Circuit)**

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS
		MIN.	TYP.	MAX.	
Static (DC) Characteristics					
Quiescent Circuit Current		20	31	44	mA
DC Voltages:					
V_1, V_2, V_3		1.2	1.9	2.4	V
V_{10}		4.9	5.6	6.1	V
V_{15}	$V_{16} = 0\text{ V}$	—	0.005	0.4	V
V_{15}	$V_{16} = 1.4\text{ V}$	4.1	5.1	5.6	V
V_{16}	$V_{15} = 1\text{--}2\text{ V}$	—	1.22	—	V
V_{12}	$V_5 \leq 0.24\text{ V}$	4.3	5.7	6.6	V
V_{12}	$V_5 \geq 0.53\text{ V}$	—	0.06	0.4	V
V_5 to cause transition of trigger (V_{12}) high to low		—	0.45	—	V
V_5 to cause transition of trigger (V_{12}) low to high		—	0.40	—	V
Dynamic Characteristics					
Input Limiting Voltage (-3 dB point)		—	12	25	μV
Recovered Audio Voltage	400 Hz Input $\geq 1\text{ mV}$ $\pm 75\text{ kHz}$ Deviation	350	520	700	mV
Frequency Window of Stop Pulse	$V_5 = 0.6\text{ V}$ Input = 100 μV	70	120	200	kHz
	$R_7 -10 = 5.1\text{ K}$ $R_7 -10 = 8.2\text{ K}$	45	75	125	
Total Harmonic Distortion, THD: *			0.50	1.0	%
AM Rejection	30% AM 100 mV Input	50	65	—	dB
	100 μV Input	35	42	—	
S/N Ratio **	100 mV Input	70	80	—	dB
	100 μV Input	55	65	—	
V_{13}	No Signal	0	0.2	0.8	V
	100 μV Input	1.4	2.2	3.2	
	100 mV Input	4.9	6.5	8.5	

* THD characteristics are essentially a function of the phase characteristics of the network connected between terminals 8, 9, and 10.

** Measured with a 30-kHz low-pass filter (-3 dB at 30 kHz, 18 dB/octave).

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CA3209E

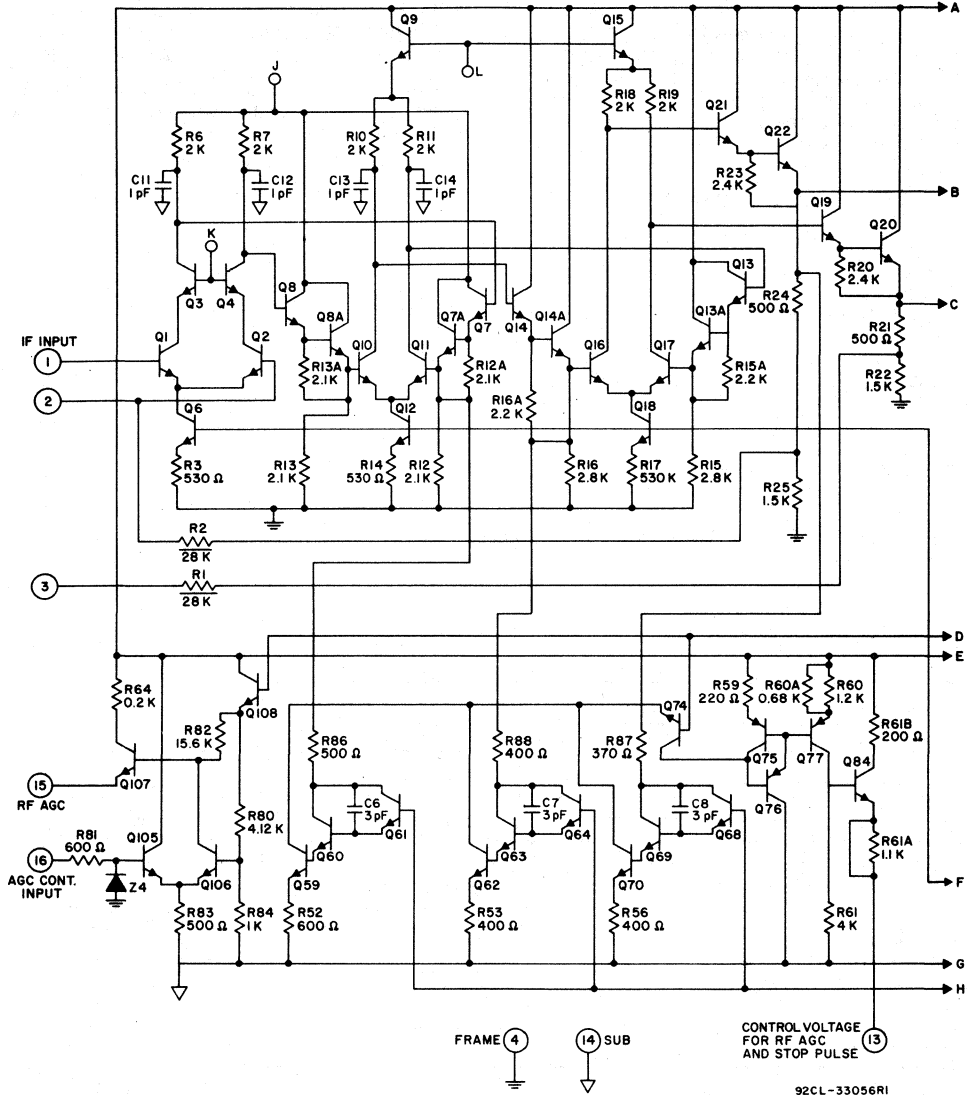


Fig. 2 - Schematic diagram of CA3209E
(continued on next page).

Linear Integrated Circuits

CA3209E

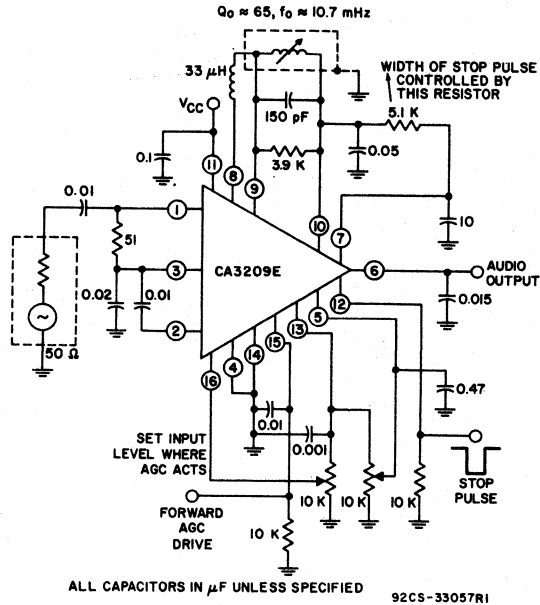


Fig. 3 - Test circuit.

MOS/FET Devices

Technical Data

RCA MOSFETs (MOS Insulated-Gate Field-Effect Transistors)

RCA MOSFET Story

RCA MOS insulated-gate field-effect transistors are N-channel, depletion-type silicon devices, and are available in both single-gate and dual-gate types. Both types offer the advantages of extremely high input resistance, low input capacitance, very low feedback capacitance, high forward transconductance, and low noise at very high frequencies. Because of their insulated-gate construction, these devices have extremely low leakage currents which are relatively insensitive to temperature variations. In addition, their drain currents have a negative temperature coefficient which

makes "thermal runaway" virtually impossible.

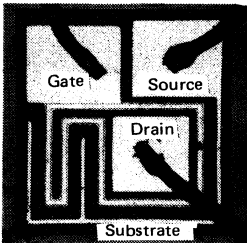
The extremely high input resistance of RCA MOS transistors permits the use of simple biasing techniques. It also makes these devices capable of handling relatively large positive and negative input-signal excursions without degradation of input impedance due to diode-current loading. Because of this capability, MOS transistors have considerably greater dynamic ranges than junction-type field-effect transistors and bipolar transistors of comparable ratings, and can provide superior perform-

ance in amplifier circuits utilizing automatic gain control. Furthermore, the extremely high input resistances of these devices impose virtually no loading on AGC voltage sources.

In addition to the features described above, RCA MOS transistors are notably superior to other solid-state devices in cross-modulation characteristics, and in their relative freedom from spurious responses. These transistors are also characterized by zero offset voltage—a feature which makes them especially desirable for chopper applications.

Applications

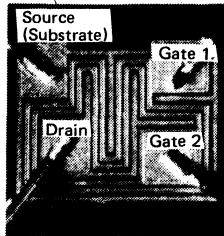
RCA Single-Gate MOS Transistors provide outstanding performance in applications requiring extremely high input impedance. They are also capable of providing high power gains at frequencies up to approximately 250 MHz. Typical applications for these devices include



rf-amplifier, mixer, and oscillator service in mobile and fixed communications equipment and in home entertainment equipment, and as audio and wide-band amplifiers, variable attenuators, choppers, and current limiters in industrial instrumentation and control equipment. *RCA single-gate MOS transistors also feature a separate terminal permitting connection to the bulk (substrate).*

RCA Dual-Gate MOS Transistors feature a series arrangement of two separate channels, each channel having an independent control gate. This arrangement

results in substantially lower feedback capacitance, greater gain, remote AGC capability in rf-amplifier applications, substantially better cross-modulation characteristics and lower spurious response than are provided by single-gate types. The availability of two independent control gates also offers unique advantages for chopper, clipper, and gated-amplifier service, and for applications involving the combination of two or

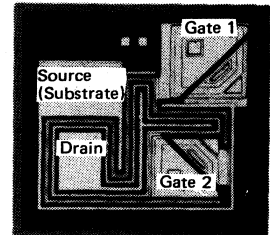


more signals, such as mixers, product detectors, color demodulators, and balanced modulators.

RCA Dual-Gate-Protected RF MOS Transistors incorporate back-to-back diodes for each gate within the same silicon MOSFET pellet. The major technical challenge in the development of these new MOSFETs was that gate protection must not significantly degrade the RF

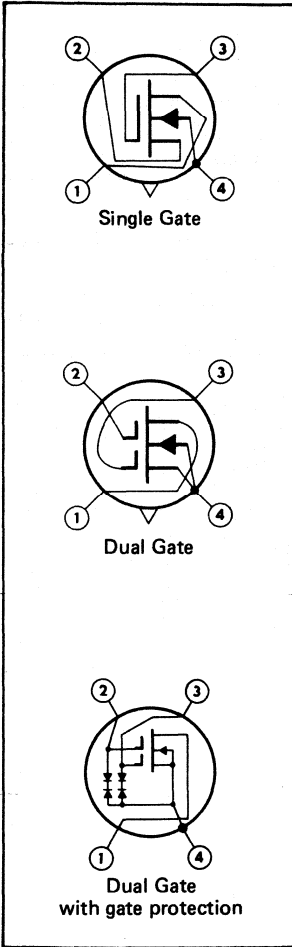
performance. Special back-to-back diodes were developed as the answer to this objective.

The back-to-back diodes are diffused directly into the MOS pellet and are electronically connected between each insulated gate and the FET's source; this arrangement permits the device to handle a wide dynamic signal swing and still provide excellent RF performance. The low junction capacitance of the diodes adds little to the total capacitance shunting the gate. Furthermore, the resistive components of these diodes are such that they do not materially affect the overall noise performance of the unit.



The net result is a MOSFET which protects against static discharge during handling operations without the need for external shorting mechanisms, protects against in-circuit transients, and is more rugged than any other solid-state amplifier providing comparable performance.

RCA MOSFETs (MOS Insulated-Gate Field-Effect Transistors)



RCA Single-gate and dual-gate MOSFETs offer these features and benefits to the designer:

- Extremely high input resistance – imposes virtually no loading on AGC voltage source
- Very low feedback capacitance
- High forward transconductance
- Wide dynamic range – handle positive and negative input-signal excursions without diode-current loading
- Wide AGC range
- Virtually no AGC power required
- Very low gate leakage current – relatively insensitive to temperature variations
- Negative temperature coefficient of drain current – makes “thermal runaway” virtually impossible
- Zero offset voltage – especially desirable for chopper applications
- Bulk (substrate) terminal available on all single-gate types
- Substantially better cross-modulation characteristics and lower spurious response than junction-type FET’s and bipolar transistors
- Operating-temperature range, all types: –65 to +175°C

RCA Dual-gate MOSFETs offer these additional features

- Extremely low feedback capacitance
- Reduced oscillator feedthrough
- Higher frequency capabilities
- Exceptionally high forward transconductance
- Higher vhf power gain
- No neutralization required
- Increased gain reduction with AGC
- Cross-modulation characteristics actually improve as device approaches cutoff
- Unique advantages for mixer, product-detector, remote gain control, color-demodulator, balanced-modulator, chopper, clipper, and gated-amplifier applications
- Can function as a triode equivalent device when the two gates are connected to a single terminal

Quick-Selection Guide

Application	Industrial Types											Consumer Types																										
	Single-Gate					Dual-Gate	Dual-Gate Protected	Single-Gate	Dual-Gate					Dual-Gate Protected																								
	3N128	3N138	3N139	3N142	3N143	3N152	3N153	3N154	3N140	3N141	3N159	3N187	3N200	40819	40467A	40468A	40559A	40600	40601	40602	40603	40604	3N204	3N205	3N206	40673	3N211	3N212	3N213	40820	40821	40822	40823	40841				
RF Amplifier, Mixer	■			■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■		
Chopper		■					■																														■	
General-Purpose Amplifier			■	■																■																	■	
Oscillator	■		■	■	■			■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	■	
Low-Noise																																						
Low-Leakage		■																		■	■	■	■															
High-Gain																																						
Gain-Controlled																																						
Premium-Performance																																						

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RCA MOSFETs (MOS Insulated-Gate Field-Effect Transistors)

RCA MOSFETs for RF application and for instrumentation, chopper, and control application in industrial and military equipment

Description and Application				Absolute Maximum Ratings# At T _A = 25° C					
RCA Type	Description	Usable Frequency Range MHz	Circuits and End-Use Equipment	Drain-to-Source Volts V _{DS}		Gate 1-to-Source Volts V _{G1S}		Gate 2-to-Source Volts V _{G2S}	
				Neg.	Pos.	DC	Peak AC	DC	Peak AC
SINGLE-GATE DEVICES[■]									
For RF Applications									
3N128	High-Gain, Low-Noise RF Amplifier, IF Amplifier, Oscillator	to 250	High-Impedance Timing Circuits, Detectors, Frequency Multipliers, Phase Splitters, Pulse Stretchers, Voltage-Controlled Attenuators, Electrometer Amplifiers, High-Impedance Differential Amplifiers in VHF Fixed and Mobile Communications Equipment and for Instrumentation and Navigation	0	+20	+1 to -8	±15	-	-
3N139	High-Gain RF Amplifier, Video Amplifier, IF Amplifier For Use With High Drain Supply Voltage (+35 V max.)	to 250		0	+35	±10	±14	-	-
3N142	High-Gain Low-Noise RF Amplifier and Oscillator	to 175		0	+20	+1 to -8	±15	-	-
3N143	Mixer and Oscillator	to 250		0	+20	+1 to -8	±15	-	-
3N152	Low-Noise, Premium-Performance RF Amplifier	to 250		0	+20	+1 to -8	±15	-	-
3N154	Low-Leakage Premium-Performance RF Amplifier	to 250		0	+20	+1 to -8	±15	-	-
For Chopper, Instrumentation, and Control Applications									
3N128	High-Gain DC Amplifier	to 250	Servo Amplifiers, Telemetry Amplifiers, Computer Operational Amplifiers, Sampling Circuits, Electrometer Amplifiers in Communications, Navigation, and Instrumentation Equipment and Control Circuits	0	+20	+1 to -8	±15	-	-
3N138	For Chopper and Multiplex Service to 60 MHz DC Amplifier	to 250		0	+35	±10	±14	-	-
3N139	DC Amplifier, Video Amplifier, RF Amplifier with High Drain Voltage Capability (+35 V max.)	to 250		0	+35	±10	±14	-	-
3N142	DC Amplifier	to 175		0	+20	+1 to -8	±15	-	-
3N153	For Chopper and Multiplex Service to 60 MHz DC Amplifier	to 250		0	+20	+6 to -8	±14	-	-
DUAL-GATE DEVICES WITH INTEGRAL GATE PROTECTION									
For RF Applications									
3N140	High-Gain, Low-Noise Gain-Controlled RF Amplifier, IF Amplifier	to 300	Communications Equipment	0	+20	+1 to -8	+20 to -8	-8 to 40% of V _{DS}	-8 to +20

RCA MOSFETs (MOS Insulated-Gate Field-Effect Transistors)
RCA MOSFETs for RF application and for instrumentation,
chopper, and control application in industrial and military equipment

Electrical Characteristics at T _A = 25°C												
Typical Gate-Leakage (Input) Resistance r _{GS} Ohms	Offset Voltage V _O [•] Volts	Typical "ON" Resistance r _{DS(on)} Ohms	Typical Power Gain G _{PS} dB	Typical Noise Figure NF dB	Noise Figure and Power Gain Test Frequency MHz	Typical Forward Transconductance g _{fs} umho	Max. Gate Leakage Current I _{GSS} nA	Typ. Input Capacitance C _{iss} pF	Typical Gate-to-Source Cutoff Voltage V _{GS}	Typical Reverse Transfer Capacitance (Feedback) C _{rss} pF	Application Note and Data Sheet File No.	RCA Type
SINGLE-GATE DEVICES[•]												
For RF Applications												
—	—	—	16*	3.5	200	7500	5	5.5	-3	0.25	AN3193 AN3341	309 3N128
—	—	—	—	—	—	6000	1 0.1 nA Typ.	3	-6 max.	0.2	ST3703	284 3N139
—	—	—	16*	2.5	100	7500	1 0.1 pA Typ.	5.5	-3	0.22	ST3703	286 3N142
—	—	—	13.5 (conv.)	—	f _{IN} =200 f _{OUT} =30	7500	200	5.5	-3	0.25	AN3193 AN3341	309 3N143
—	—	—	16*	2.5	200	7500	1 0.1 pA Typ.	5.5	-3	0.25	ST3703	314 3N152
Closely Controlled Zero-Bias Drain Current (I _{DSS}), 10 to 25 mA			16*	3.5	200	7500	5 0.1 pA Typ.	5.5	-3	0.25	—	335 3N154
For Chopper, Instrumentation, and Control Applications												
1014	0	200	16*	3.5	200	7500	5	5.5	-3	0.25	AN3193 AN3341	309 3N128
1014	0	180#	—	—	—	6000	10 pA	3	-10 max.	0.2	AN3452	283 3N138
1014	0	200	—	—	—	6000	1	3	-6 max.	0.2	ST3703	284 3N139
1012	0	200	16*	2.5	100	7500	1 0.1 pA Typ.	5.5	-3	0.22	ST3703	286 3N142
1010	0	200##	—	—	—	10000	50 pA	6	-2	0.34	—	320 3N153
DUAL-GATE DEVICES WITH INTEGRAL GATE PROTECTION												
For RF Applications												
—	—	—	—	3.5	18	10000	1 [▲]	5.5	-2 [▲]	0.02	—	285 3N140

RCA MOSFETs (MOS Insulated-Gate Field-Effect Transistors)

RCA MOSFETs for RF application and for instrumentation, chopper, and control application in industrial and military equipment—cont'd.

Description and Application				Absolute Maximum Ratings# At T _A = 25°C					
RCA Type	Description	Usable Frequency Range MHz	Circuits and End-Use Equipment	Drain-to-Source Volts V _{DS}		Gate 1-to-Source Volts V _{G1S}		Gate 2-to-Source Volts V _{G2S}	
				Neg.	Pos.	DC	Peak AC	DC	Peak AC
3N141	Mixer, Product Detector, Modulator	to 300	Aircraft and Marine Vehicular Receivers	0	+20	+1 to -8	+20 to -8	-8 to 40% V _{DS}	-8 to +20
3N159	High-Gain, Very Low-Noise, Gain-Controlled RF Amplifier	to 300		0	+20	+1 to -8	+20 to -8	-8 to 40% V _{DS}	-8 to +20
3N187	RF Amplifier, Mixer, and IF Amplifier	to 300	CATV and MATV Equipment	-0.2	+20	+3 to -6	±6	-6 to 30% V _{DS}	±6
3N200	High-Gain RF Amplifier, Mixer, and IF Amplifier	to 500	Telemetry and Multiplex Equipment	-0.2	+20	+3 to -6	±6	-6 to 30% V _{DS}	±6
40819	RF Amplifier, Mixer, and IF Amplifier	to 300		-0.2	+25	+3 to -6	±6	-6 to 40% V _{DS}	±6
For Chopper, Instrumentation, and Control Applications									
3N140	DC Amplifier	to 300	See Choppers Instrumentation, and Control Applications on Page 4	0	+20	+1 to -8	+20 to -8	-8 to 40% V _{DS}	-8 to +20
3N141	DC Amplifier	to 300		0	+20	+1 to -8	+20 to -8	-8 to 40% V _{DS}	-8 to +20
40841	General-Purpose	to 500		-4.5 to +3				-4.5 to 40% V _{DS}	

For a Maximum Drain Current (I_D) = 50 mA, Device Dissipation (P_T) = 330 mW

■ Bulk (Substrate) is brought out as a separate terminal lead (connected to case internally).

RCA MOSFETs for RF application in consumer equipment

Description and Application				Absolute Maximum Ratings # at T _A = 25°C					
RCA Type	Description	Usable Frequency Range MHz	End-Use Equipment	Drain-to-Source Volts V _{DS}		Gate 1-to-Source Volts V _{G1S}		Gate 2-to-Source Volts V _{G2S}	
				Neg.	Pos.	DC	Peak AC	DC	Peak AC
SINGLE-GATE DEVICES[■]									
40467A	200-MHz General-Purpose RF Amplifier and Oscillator	to 220	VHF Amplifier Applications in Commercial and Industrial Electronic Equipment	0	+20	+1 to -8	±15	—	—

RCA MOSFETs (MOS Insulated-Gate Field-Effect Transistors)

RCA MOSFETs for RF application and for instrumentation, chopper, and control application in industrial and military equipment—cont'd.

Electrical Characteristics at T _A = 25°C												
Typical Gate-Leakage (Input) Resistance r _{GS} Ohms	Offset Voltage V ₀ • Volts	Typical "ON" Resistance r _{DS(on)} Ohms	Typical Power Gain G _{PS} dB	Typical Noise Figure NF dB	Noise Figure and Power Gain Test Frequency MHz	Typical Forward Transconductance g _{fs} umho	Max. Gate Leakage Current I _{GSS} nA	Typ. Input Capacitance C _{iSS} pF	Typical Gate-to-Source Cutoff Volts V _{GS}	Typ. Rev. Transfer Capacitance (Fdbk) C _{rSS} pF	Application Note and Data Sheet File No.	RCA Type
—	—	—	17 (conv.)	—	f _{IN} = 200 f _{OUT} =30	10000	1 [▲]	5.5	-2 [▲]	0.02	— 285	3N141
—	—	—	16 min.	2.5	200	10000	1 [▲]	5.5	-2 [▲]	0.02	— 326	3N159
—	—	—	18	3.5	200	12000	50 [▲]	6	-2 [▲]	0.02	ST3703 AN4018 436	3N187
—	—	—	12.5	3.9	400	15000	50 [▲]	6	-1 [▲]	0.02	ST3703 AN4018 437 AN4431	3N200
—	—	—	18	3.5	200	12000	50 [▲]	6	-2 [▲]	0.02	ST3703 AN4018 463	40819
For Chopper, Instrumentation, and Control Applications												
10 ¹²	0	—	—	—	—	10000	1 [▲]	5.5	-2 [▲]	0.02	— 285	3N140
10 ¹²	0	—	—	—	—	10000	1 [▲]	5.5	-2 [▲]	0.02	— 285	3N141
—	—	—	32 24 (conv.)	0.46 [†]	Gps at 44 MHz	12000	60 [▲]	6.5	-2 [▲]	0.20	— 498	40841

* Fixed Neutralization
Typical "OFF" resistance
[r_{DS(off)}] = 10¹¹ Ω
Typical "OFF" resistance
[r_{DS(off)}] = 10¹⁰ Ω

• In measurements of Offset Voltage, thermocouple effects and contact potentials in the measurement setup may cause erroneous readings of 1 microvolt or more. These errors may be minimized by the use of solder having a low thermal e.m.f., such as Leads & Northrup No. 107-1.0.1, or equivalent.

■ Bulk (Substrate) is brought out as a separate terminal lead connected to case internally.
▲ Value applies to each gate
† Audio spot at 1 kHz.

RCA MOSFETs for RF application in consumer equipment

Electrical Characteristics at T _A = 25°C											
Typical Power Gain G _{PS} dB	Typical Noise Figure NF dB	Noise Figure and Power Gain Test Frequency MHz	Typical Forward Transconductance g _{fs} umho	Max. Gate Leakage Current I _{GSS} mA	Typ. Input Capacitance C _{iSS} pF	Typical Gate-to-Source Cutoff Volts		Typical Reverse Transfer Capacitance (Feedback) C _{rSS} pF	Application Note and Data Sheet File No.	RCA Type	
						Gate 1 V _{G1S}	Gate 2 V _{G2S}				
SINGLE-GATE DEVICES[■]											
16	3.5	200	7500	1	5.5	-8 max.	—	0.16	ST-2990A 324	40467A	

RCA MOSFETs (MOS Insulated-Gate Field-Effect Transistors)
RCA MOSFETs for RF application in consumer equipment - cont'd.

Description and Application				Absolute Maximum Ratings # at T _A = 25°C					
RCA Type	Description	Usable Frequency Range MHz	End-Use Equipment	Drain-to-Source Volts V _{DS}		Gate 1-to-Source Volts V _{G1S}		Gate 2-to-Source Volts V _{G2S}	
				Neg.	Pos.	DC	Peak AC	DC	Peak AC
40468A	100-MHz RF Amplifier	to 125	FM and AM/FM Receivers	0	+20	+1 to -8	±15	-	-
40559A	100-MHz Oscillator or Mixer	to 125		0	+20	+1 to -8	±15	-	-
DUAL-GATE DEVICES									
40600	200-MHz Gain-Controlled RF Amplifier	to 250	VHF TV Tuners	0	+20	+1 to -8	+20 to -8	-8 to 40% of V _{DS}	-8 to +20
40601	200-MHz Mixer	to 250		0	+20	+1 to -8	+20 to -8	-8 to 40% of V _{DS}	-8 to +20
40602	44-MHz Gain-Controlled IF Amplifier	to 75	TV Receivers	0	+20	+1 to -8	+20 to -8	-8 to 40% of V _{DS}	-8 to +20
40603	100-MHz Gain-Controlled IF Amplifier	to 150	FM Receivers	0	+20	+1 to -8	+20 to -8	-8 to 40% of V _{DS}	-8 to +20
40604	100-MHz Mixer	to 150		0	+20	+1 to -8	+20 to -8	-8 to 40% of V _{DS}	-8 to +20
DUAL-GATE DEVICES WITH INTEGRAL GATE-PROTECTION									
3N204	Low-Noise	RF Amplifier	to 220	VHF TV Receivers	0	+25	P _T = 360 mW		
3N205		Mixer	to 220		0	+25	P _T = 360 mW		
3N206		IF Amplifier	to 220		0	+25	P _T = 360 mW		
3N211		RF Amplifier	to 220		0	+27	P _T = 360 mW		
3N212		Mixer	to 220		0	+27	P _T = 360 mW		
3N213		IF Amplifier	to 220		0	+35	P _T = 360 mW		

RCA MOSFETs (MOS Insulated-Gate Field-Effect Transistors)
RCA MOSFETs for RF application in consumer equipment - cont'd.

Electrical Characteristics at T _A = 25°C										
Typical Power Gain	Typical Noise Figure	Noise Figure and Power Gain Test Frequency	Typical Forward Transconductance	Max. Gate Leakage Current	Typ. Input Capacitance	Typical Gate-to-Source Cutoff Volts		Typical Reverse Transfer Capacitance (Feedback)	Application Note and Data Sheet File No.	RCA Type
						Gate 1 VG1S	Gate 2 VG2S			
17	3.5	100	7500	1	5.5	-8 max.	-	0.16	AN-3453 323 AN-3535	40468A
22 (conv.)	-	f _{IN} = 100 f _{OUT} = 10.7	2800 (conv.)	1	5.5	-8 max.	-	0.17	AN-3535 323	40559A
DUAL-GATE DEVICES										
20	3.5	200	10000	1	5.5	-3	-3	0.02	ST-3703 333	40600
14 (conv.)	-	200	2800 (conv.)	1	5.5	-3	-3	0.02	ST-3703 333	40601
28	-	44	10000	1	5.5	-3	-3	0.02	ST-3703 333	40602
24	3	100	10000	1	5.5	-3	-3	0.02	ST-3703 334	40603
23 (conv.)	-	f _{IN} = 100 f _{OUT} = 10.7	2800 (conv.)	1	5.5	-3	-3	0.02	ST-3703 334	40604
DUAL-GATE DEVICES WITH INTEGRAL GATE-PROTECTION										
24 (Insertion)	2.5	200	14	10 ^A	5	-4 max.	-4 max.	0.03 max.	- 959	3N204
23 (conv.)	-	200	14	10 ^A	5	-4 max.	-4 max.	0.03 max.	- 959	3N205
30 (Insertion)	3	45	12	10 ^A	5	-4 max.	-4 max.	0.03 max.	- 959	3N206
30 (Insertion)	2.5	-	30	10 ^A	7	-5.5 max.	-2.5 max.	0.05 max.	- 875	3N211
25 (conv.)	-	200	30	10 ^A	7	-4 max.	-4 max.	0.05 max.	- 875	3N212
31 (Insertion)	3	45	25	10 ^A	7	-5.5 max.	-4 max.	0.05 max.	- 875	3N213

RCA MOSFETs (MOS Insulated-Gate Field-Effect Transistors)

RCA MOSFETs for RF application in consumer equipment - cont'd.

Description and Application				Absolute Maximum Ratings # at T _A = 25°C					
RCA Type	Description	Usable Frequency Range MHz	End-Use Equipment	Drain-to-Source Volts V _{DS}		Gate 1-to-Source Volts V _{G1S}		Gate 2-to-Source Volts V _{G2S}	
				Neg.	Pos.	DC	Peak AC	DC	Peak AC
40673	200 MHz RF Amplifier, Mixer, and IF Amplifier	to 400	Aircraft and Marine Receivers CATV and MATV Equipment	-0.2	+20	+1 to -6	±6	-6 to 30% of V _{DS}	±6
40820	RF Amplifier	to 250	VHF TV Tuners	-0.2	+20	+3 to -6	±6	-6 to 40% of V _{DS}	±6
40821	RF Mixer	to 250		-0.2	+20	+3 to -4.5	±6	-4.5 to 40% of V _{DS}	±6
40822	RF Amplifier	to 250	FM Tuners	-0.2	+18	+3 to -6	±6	-6 to 40% of V _{DS}	±6
40823	RF Mixer	to 150		-0.2	+18	+3 to -4.5	±6	-4.5 to 40% of V _{DS}	±6

For a Maximum Drain Current (I_D) = 50 mA,
Device Dissipation (P_T) = 330 mW
Operating Temperature Range (T_A) = -65°C to +121°C

■ Bulk (Substrate) is brought out as a separate terminal lead (connected to case internally)

Handling of MOSFETs which do not include gate-protection circuits

Insulated-Gate Metal-Oxide-Semiconductor Field-Effect Transistors (MOSFETs), like bipolar high-frequency transistors, are susceptible to gate insulation damage by the electrostatic discharge of energy through the devices. Electrostatic discharges can occur in a MOSFET if a type with an unprotected gate is picked up and the static charge, built in the handler's body capacitance, is discharged through the device. With proper handling and applications procedures, however, MOS transistors are currently being extensively used in production by numerous equipment manufacturers in military, industrial, and consumer applications, with virtually no problems of damage due to electrostatic discharge.

In some MOSFETs, diodes are electrically connected between each insulated gate and the transistor's source. These diodes offer protection against static discharge and in-circuit transients without the need for external shorting mechanisms.

MOSFETs which do not include gate-protection diodes can be handled safely if the following basic precautions are taken:

1. Prior to assembly into a circuit, all leads should be kept shorted together either by the use of metal shorting springs attached to the device by the vendor, or by the insertion into conductive material such as "ECCOSORB" LD26" or equivalent.
(NOTE: Polystyrene *insulating* "SNOW" is not sufficiently conductive and should not be used.)
2. When devices are removed by hand from their carriers, the hand being used should be grounded by any suitable means, for example, with a metallic wristband.
3. Tips of soldering irons should be grounded.
4. Devices should never be inserted into or removed from circuits with power on.

* Trademark: Emerson and Cumming, Inc.

RCA MOSFETs (MOS Insulated-Gate Field-Effect Transistors)

RCA MOSFETs for RF application in consumer equipment - cont'd.

Electrical Characteristics at $T_A = 25^\circ\text{C}$										
Typical Power Gain Gps dB	Typical Noise Figure NF dB	Noise Figure and Power Gain Test Frequency MHz	Typical Forward Transconductance g_{fs} umho	Max. Gate Leakage Current I_{GSS} mA	Typ. Input Capacitance C_{iss} pF	Typical Gate-to-Source Cutoff Volts		Typical Reverse Transfer Capacitance (Feedback) C_{rss} pF	Application Note and Data Sheet File No.	RCA Type
						Gate 1 VG1S	Gate 2 VG2S			
18	3.5	200	12000	50	6	-2	-2	0.02	ST-3703 381 AN-4018	40673
17	4.5	200	12000	50	6	-1	-1	0.02	ST-3703 464 AN4018	40820
11 (conv.)	-	$f_{IN}=200$ $f_{OUT}=44$	12000	50	6	-1	-1	0.02	ST-3703 464 AN-4018	40821
24	3.5	100	12000	50	6.5	-2	-2	0.02	ST-3703 465 AN-4018	40822
18 (conv.)	-	$f_{IN} = 100$ $f_{OUT}=10.7$	12000	50	6.5	-2	-2	0.02	ST-3703 465 AN4018	40823

■ Bulk (Substrate is brought out as a separate terminal lead (connected to case internally).

▲ Value applies to each gate

APPLICATION NOTES

No.	Title
AN3193	"Application Considerations for the RCA-3N128 VHF MOS Field-Effect Transistor"
AN3341	"VHF Mixer Design Using the RCA-3N128 MOS Transistor"
AN3435	"Cross-Modulation Effects in Single-Gate and Dual-Gate MOS FET Transistors"
AN3452	"Chopper Circuits Using RCA MOS Field-Effect Transistors"
AN3453	"An FM Tuner Using an RCA-40468 MOS-Transistor RF Amplifier"
AN3535	"An FM Tuner Using Single-Gate MOS Field-Effect Transistors as RF Amplifier and Mixer"
AN4018	"Design of Gate-Protected MOS Field-Effect Transistors"
AN4125	"MOS FET Biasing Techniques"
AN4431	"RF Applications of the Dual-Gate MOS FET up to 500 MHz"
AN4590	"Using MOS FET IC's in Linear Circuit Applications"
ST3486	"Application of Dual-Gate MOS Field-Effect Transistors in Practical Radio Receivers"
ST3520	"Insulated-Gate Field-Effect Transistors in Oscillator Circuits"

A copy of a Technical Bulletin for any of the MOSFET types or a copy of the Application Notes shown above, is available on request from RCA Solid State Division, Box 3200, Somerville, N.J. 08876. To expedite receipt of the requested data, please refer to the Technical Bulletin File No. shown on the Characteristics Charts, or to the Application Note No.

Supplementary Information

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RCA High-Reliability Bipolar IC's

RCA MIL-STD-883 Slash-Series Linear IC's

The RCA CA3000 slash-series of high-reliability linear integrated circuits includes a broad range of types for use in satellites and other aerospace, military, and critical industrial applications in which maintenance is extremely difficult. These integrated circuits are processed and screened in accordance with MIL-STD-883, Method 5004 format.

The RCA CA3000 slash-series types are supplied to three

screening levels (/1, /3, and /3W) that meet the electrical, mechanical, and environmental test methods and procedures established for microelectronics in MIL-STD-883.

RCA CA3000-series IC products listed below are commercial products that can be supplied to standard RCA screening levels or to specialized customer requirements on a custom basis.

CA3000-Series Linear IC's and MOS/FET's

Type No.	Description	No. of Leads	Type No.	Description	No. of Leads
CA101A	Operational Amplifiers	8	CA3085A	Voltage Regulators	8
CA723	Voltage Regulators	10	CA3085B	Voltage Regulators	8
CA741	Operational Amplifiers	8	CA3094	Programmable Power Switch/ Amplifier	8
CA747	Dual Operational Amplifiers	10	CA3094A	Programmable Power Switch/ Amplifier	8
CA748	Operational Amplifiers	8	CA3094B	Programmable Power Switch/ Amplifier	8
CA1558	Dual Operational Amplifiers	8	CA3100	BiMOS Operational Amplifiers	8
CA3000	Differential Amplifiers	10	CA3118	Transistor Arrays	12
CA3001	Differential Amplifiers	12	CA3118A	Transistor Arrays	12
CA3002	Differential Amplifiers	10	CA3130	BiMOS Operational Amplifiers	8
CA3004	Differential Amplifiers (RF)	12	CA3130A	BiMOS Operational Amplifiers	8
CA3006	Differential Amplifiers (RF)	12	CA3140	BiMOS Operational Amplifiers	8
CA3015A	Operational Amplifiers	12	CA3140A	BiMOS Operational Amplifiers	8
CA3018A	Transistor Arrays	12	CA3160	BiMOS Operational Amplifiers	8
CA3019	Diode Arrays	10	CA3160A	BiMOS Operational Amplifiers	8
CA3020A	Wide-Band Power Amplifiers	12	CA3260T	BiMOS Operational Amplifier	8
CA3026	Dual Differential Amplifier Arrays	12	CA3260AT	BiMOS Operational Amplifier	8
CA3028B	Differential Amplifiers (RF)	8	CA3290	BiMOS Dual Voltage Comparators	8
CA3039	Diode Arrays	12			
CA3045	Transistor Arrays	14			
CA3049	Dual Differential Amplifier Arrays	12			
CA3058	Zero-Voltage Switches	14			
CA3078	Micropower Operational Amplifiers	8			
CA3080	Variable Operational Amplifiers	8			
CA3081	Transistor Arrays	16			
CA3082	Transistor Arrays	16			
CA3085	Voltage Regulators	8			

MOS/FET's

HR3N187	Dual-Gate MOS Field-Effect Transistor	4
HR3N200	Dual-Gate MOS Field-Effect Transistor	4

Note:

High-reliability versions of most commercially available CA3000-series linear IC's not listed above can also be supplied on a custom basis.

Screening Levels for RCA MIL-STD-883 Slash-Series Linear Integrated Circuits

RCA Levels	Screening Levels MIL-STD-883, Method 5004 Format	Application	Description
For Packaged Devices (D, F, K, S, T, or V1 Suffix)			
/1	Class S with Condition B Precap Visual Inspection	Aerospace and Missiles	For devices intended for use where maintenance and replacement are impossible and reliability is imperative
/3	Class B	Military and Industrial For example, in Airborne Electronics	For devices intended for use where maintenance and replacement can be performed but are difficult and expensive
/3W	Class B with High- and Low-Temperature DC Testing omitted		
For Chips (H Suffix)			
/M	Condition B Precap Visual Inspection with Traceability and Certificate of Compliance Required	Military and Industrial	For general applications

Supplementary Information

Dimensional Outlines

CERAMIC DUAL-IN-LINE PACKAGES

(D) Suffix (JEDEC MO-001-AD) 14-Lead

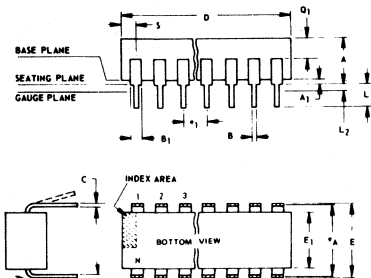
SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
A	0.120	0.160		3.06	4.06
A ₁	0.020	0.065		0.51	1.65
B	0.014	0.020		0.356	0.508
B ₁	0.050	0.065		1.27	1.65
C	0.008	0.012	1	0.204	0.304
D	0.745	0.770		18.93	19.55
E	0.300	0.325		7.62	8.25
E ₁	0.240	0.260		6.10	6.60
e ₁	0.100 TP		2	2.54 TP	
e _A	0.300 TP		2, 3	7.62 TP	
L	0.125	0.150		3.18	3.81
L ₂	0.000	0.030		0.000	0.76
α	0°	15°	4	0°	15°
N	14		5	14	
N ₁	0		6	0	
Q ₁	0.050	0.085		1.27	2.15
S	0.065	0.090		1.66	2.28

92SS-4411R2

(D) Suffix (JEDEC MO-001-AE) 16-Lead

SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
A	0.120	0.160		3.05	4.06
A ₁	0.020	0.065		0.51	1.65
B	0.014	0.020		0.356	0.508
B ₁	0.035	0.065		0.89	1.65
C	0.008	0.012	1	0.204	0.304
D	0.745	0.785		18.93	19.93
E	0.300	0.325		7.62	8.25
E ₁	0.240	0.260		6.10	6.60
e ₁	0.100 TP		2	2.54 TP	
e _A	0.300 TP		2, 3	7.62 TP	
L	0.125	0.150		3.18	3.81
L ₂	0.000	0.030		0.000	0.76
α	0°	15°	4	0°	15°
N	16		5	16	
N ₁	0		6	0	
Q ₁	0.050	0.085		1.27	2.15
S	0.015	0.060		0.39	1.52

92SS-4286R5



NOTES:
Refer to Rules for Dimensioning (JEDEC Publication No. 95) for Axial Lead Product Outlines.

- When this device is supplied solder dipped, the maximum lead thickness (narrow portion) will not exceed 0.013".
- Leads within 0.005" (0.12 mm) radius of True Position (TP) at gauge plane with maximum material condition and unit installed.
- e_A applies in zone L₂ when unit installed.
- α applies to spread leads prior to installation.
- N is the maximum quantity of lead positions.
- N₁ is the quantity of allowable missing leads.

DUAL-IN-LINE PLASTIC, (E) SUFFIX AND FRIT-SEAL CERAMIC, (F) SUFFIX PACKAGES

(E) Suffix 8-Lead Plastic (Mini-DIP)

SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
A	0.155	0.200		3.94	5.08
A ₁	0.020	0.050		0.508	1.27
B	0.014	0.020		0.356	0.508
B ₁	0.035	0.065		0.889	1.65
C	0.008	0.012	1	0.203	0.304
D	0.370	0.400		9.40	10.16
E	0.300	0.325		7.62	8.25
E ₁	0.240	0.260		6.10	6.60
e ₁	0.100 TP		2	2.54 TP	
e _A	0.300 TP		2, 3	7.62 TP	
L	0.125	0.150		3.18	3.81
L ₂	0.000	0.030		0.000	0.762
α	0	15	4	0	15
N	8		5	8	
N ₁	0		6	0	
Q ₁	0.040	0.075		1.02	1.90
S	0.015	0.060		0.381	1.52

92CS-24026R1

(E) and (F) Suffixes (JEDEC MO-001-AB) 14-Lead

SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
A	0.155	0.200		3.94	5.08
A ₁	0.020	0.050		0.51	1.27
B	0.014	0.020		0.356	0.508
B ₁	0.050	0.065		1.27	1.65
C	0.008	0.012	1	0.204	0.304
D	0.745	0.770		18.93	19.55
E	0.300	0.325		7.62	8.25
E ₁	0.240	0.260		6.10	6.60
e ₁	0.100 TP		2	2.54 TP	
e _A	0.300 TP		2, 3	7.62 TP	
L	0.125	0.150		3.18	3.81
L ₂	0.000	0.030		0.000	0.76
α	0°	15°	4	0°	15°
N	14		5	14	
N ₁	0		6	0	
Q ₁	0.040	0.075		1.02	1.90
S	0.065	0.090		1.66	2.28

92SS-4296R3

(F) Suffix (JEDEC MO-001-AC) 16-Lead

SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
A	0.155	0.200		3.94	5.08
A ₁	0.020	0.050		0.51	1.27
B	0.014	0.020		0.356	0.508
B ₁	0.035	0.065		0.89	1.65
C	0.008	0.012	1	0.204	0.304
D	0.745	0.785		18.93	19.93
E	0.300	0.325		7.62	8.25
E ₁	0.240	0.260		6.10	6.60
e ₁	0.100 TP		2	2.54 TP	
e _A	0.300 TP		2, 3	7.62 TP	
L	0.125	0.150		3.18	3.81
L ₂	0.000	0.030		0.000	0.76
α	0°	15°	4	0°	15°
N	16		5	16	
N ₁	0		6	0	
Q ₁	0.040	0.075		1.02	1.90
S	0.015	0.060		0.39	1.52

92CM-15967R4

(E) Suffix 18-Lead Dual-In-Line Plastic Package

SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
A	0.155	0.200		3.94	5.08
A ₁	0.020	0.050		0.508	1.27
B	0.014	0.020		0.356	0.508
B ₁	0.035	0.065		0.89	1.65
C	0.008	0.012	1	0.204	0.304
D	0.845	0.885		21.47	22.47
E	0.240	0.260		6.10	6.60
e ₁	0.100 TP		2	2.54 TP	
e _A	0.300 TP		2, 3	7.62 TP	
L	0.125	0.150		3.18	3.81
α	0°	15°	4	0°	15°
N	18		5	18	
N ₁	0		6	0	
S	0.015	0.060		0.39	1.52

92CS-30630

(E) Suffix 22-Lead Dual-In-Line Plastic Package

SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
A	0.155	0.200		3.94	5.08
A ₁	0.020	0.050		0.508	1.27
B	0.015	0.020		0.381	0.508
B ₁	0.035	0.065		0.89	1.65
C	0.008	0.012	1	0.204	0.304
D		1.120			28.44
E	0.390	0.420		9.91	10.66
E ₁	0.345	0.355		8.77	9.01
e ₁	0.100 TP		2	2.54 TP	
e _A	0.400 TP		2, 3	10.16 TP	
L	0.125	0.150		3.18	3.81
L ₂	0	0.030		0	0.762
α	2°	15°	4	2°	15°
N	22		5	22	
N ₁	0		6	0	
Q ₁	0.055	0.085		1.40	2.15
S	0.015	0.060		0.381	1.27

92CS-30830

(E) Suffix (JEDEC MO-015-AA) 24-Lead Dual-In-Line Plastic Package

SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
A	0.120	0.250		3.10	6.30
A ₁	0.020	0.070		0.51	1.77
B	0.016	0.020		0.407	0.508
B ₁	0.028	0.070		0.72	1.77
C	0.008	0.012	1	0.204	0.304
D	1.20	1.29		30.48	32.76
E	0.600	0.625		15.24	15.87
E ₁	0.515	0.580		13.09	14.73
e ₁	0.100 TP		2	2.54 TP	
e _A	0.600 TP		2, 3	15.24 TP	
L	0.100	0.200		2.54	5.00
L ₂	0.000	0.030		0.00	0.76
α	0°	15°	4	0°	15°
N	24		5	24	
N ₁	0		6	0	
Q ₁	0.040	0.075		1.02	1.90
S	0.040	0.100		1.02	2.54

92CS26938R3

Linear Integrated Circuits

Dimensional Outlines

DUAL-IN-LINE PLASTIC PACKAGE (Cont'd)

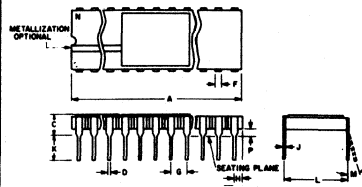
(E) Suffix 28-Lead

SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
A	0.120	0.250		3.10	6.30
A ₁	0.020	0.070		0.51	1.77
B	0.016	0.020		0.407	0.508
B ₁	0.028	0.070		0.72	1.77
C	0.008	0.012	1	0.204	0.304
D	1.400	1.490		35.56	37.85
E ₁	0.515	0.580		13.09	14.73
e ₁	0.100 TP		2	2.54 TP	
e _A	0.600 TP		2,3	15.24 TP	
L	0.100	0.200		2.54	5.00
L ₂	0.000	0.030		0.00	0.76
α	0°	15°	4	0°	15°
N	28		5	28	
N ₁	0		6	0	
Q ₁	0.045	0.080		1.14	2.03
S	0.040	0.100		1.02	2.54

92CS-31862

DUAL-IN-LINE SIDE-BRAZED CERAMIC PACKAGE

(D) Suffix 18-Lead



NOTES:

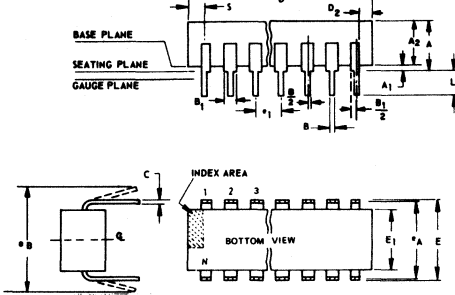
- Leads within 0.005" (0.13 mm)-radius of True Position at maximum material condition.
- Dimension "L" to center of leads when formed parallel.
- When this device is supplied solder-dipped, the maximum lead thickness (narrow portion) will not exceed 0.013" (0.33 mm).

SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
A	0.890	0.915		22.606	23.241
C	—	0.200		—	5.080
D	0.015	0.021		0.381	0.533
F	0.054 REF.		1	1.371 REF.	
G	0.100 BSC		1	2.54 BSC	
H	0.035	0.065		0.889	1.651
J	0.008	0.012	3	0.203	0.304
K	0.125	0.150		3.175	3.810
L	0.290	0.310	2	7.366	7.874
M	0°	15°		0°	15°
P	0.025	0.045		0.635	1.143
N	18			18	

92CS-27231R1

(E) Suffix (JEDEC MS-001)

16-Lead Dual-In-Line Plastic Package



NOTES:

- Refer to JEDEC Publication No. 95 JEDEC Registered and Standard Outlines for Solid State Products, for rules and general information concerning registered and standard outlines.
- Protrusions (flash) on the base plane surface shall not exceed .25 mm (.010 in.).
- The dimension shown is for full leads. "Half" leads are optional at lead positions 1, N, $\frac{N}{2}$, $\frac{N}{2} + 1$.
- Dimension D does not include mold flash or protrusions. Mold flash or protrusions shall not exceed .25 mm (.010 in.).

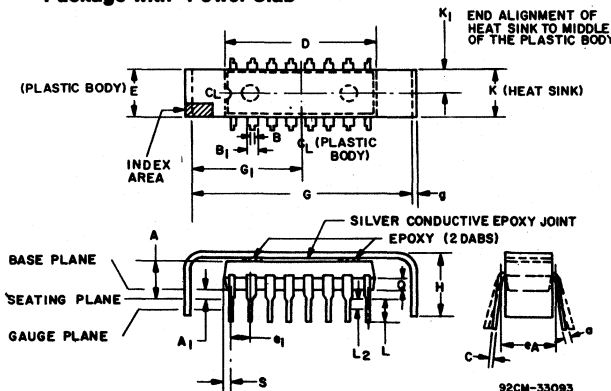
- This dimension is controlling when a particular combination of body length, lead width and lead spacing dimensions would allow lead material to overhang the ends of the package.
- E is the dimension to the outside of the leads and is measured with the leads perpendicular to the base plane (zero lead spread).
- Dimension E₁ does not include mold flash or protrusions.
- Package body and leads shall be symmetrical around center line shown in end view within .25 mm (.010 in.).
- Lead spacing e₁ shall be non-cumulative and shall be measured at the lead tip. This measurement shall be made before insertion into gauges, boards or sockets.
- This is a basic installed dimension. Measurement shall be made with the device installed in the seating plane gauge (JEDEC Outline No. GS-3, seating plane gauge). Leads shall be in true position within .25 mm (.010 in.) diameter for dimension e_A.
- e_G is the dimension to the outside of the leads and is measured at the lead tip before the device is installed. Negative lead spread is not permitted.
- N is the maximum number of lead positions.
- Dimension S at the left end of the package must equal dimension S at the right end of the package within .76 mm (.030 in.).

SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
A	—	0.210	10	—	5.33
A ₁	0.015	—	10	0.38	—
A ₂	0.115	0.195		2.93	4.95
B	0.014	0.022		0.356	0.558
B ₁	0.045	0.070	3	1.15	1.77
C	0.008	0.015		0.204	0.381
D	0.745	0.840	4	18.93	21.33
D ₂	0.005	—	5	0.13	—
E	0.300	0.325	6	7.62	8.25
E ₁	0.240	0.280	7, 8	6.10	7.11
e ₁	0.090	0.110	9	2.29	2.79
e _A	0.300 TP		10	7.62 TP	
e _B	—	0.410	11	—	10.41
L	0.115	0.150	10	2.93	3.81
N	16		12	16	
S	—	—	13	—	—

92CM-34834R1

(EM) Suffix

16-Lead Modified Dual-In-Line Plastic Package with "Power Slab"



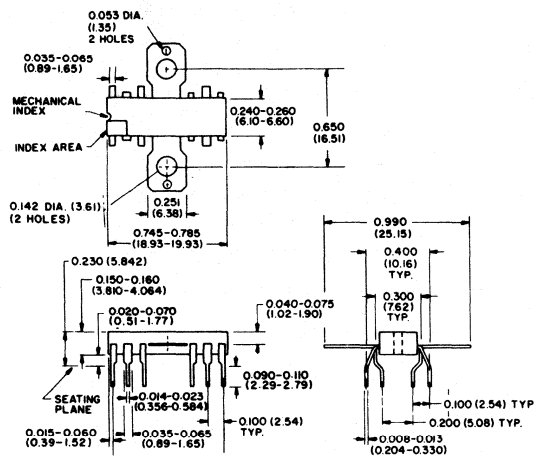
SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
A	0.155	0.200		3.94	5.08
A ₁	0.020	0.050		0.51	1.27
B	0.014	0.020		0.356	0.508
B ₁	0.035	0.065		0.89	1.65
C	0.008	0.012	1	0.204	0.304
D	0.745	0.785		18.93	19.93
E	0.240	0.280		6.10	6.80
e ₁	0.100 TP		2	2.54 TP	
e _A	0.300 TP		2,3	7.62 TP	
G ₁	0.537	0.587		13.64	14.81
G	1.125			28.58	
g	0.030	0.036		0.76	0.91
H	0.350			8.89	
K	0.250		7	6.35	
K ₁	0.093	0.187		2.36	3.99
L	0.125	0.150		3.18	3.81
L ₂	0.000	0.030		0.000	0.76
α	0°	15°	4	0°	15°
N	16		5	16	
N ₁	0		6	0	
Q	0.040	0.075		1.02	1.90
S	0.015	0.090		0.38	1.82

NOTES:

- Refer to Rules for Dimensioning (JEDEC Publication No. 95) for Axial Lead Product Outlines.
- When this device is supplied solder-dipped, the maximum lead thickness (narrow portion) will not exceed 0.013" (0.33 mm).
 - Leads within 0.005" (0.12 mm) radius of True Position (TP) at gauge plane with maximum material condition and unit installed.
 - e_A applies in zone L₂ when unit installed.
 - α applies to spread leads prior to installation.
 - N is the maximum quantity of lead positions.
 - N₁ is the quantity of allowable missing leads.
 - Subject to 0.280" (7.11 mm) permissible at points of debossing.

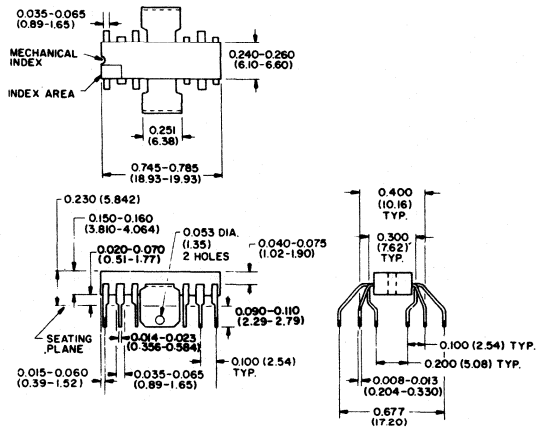
QUAD-IN-LINE PLASTIC PACKAGES

(QM) Suffix
Modified 16-Lead with Integral Flat Wing-Tab Heat Sink



92CM-25049R3

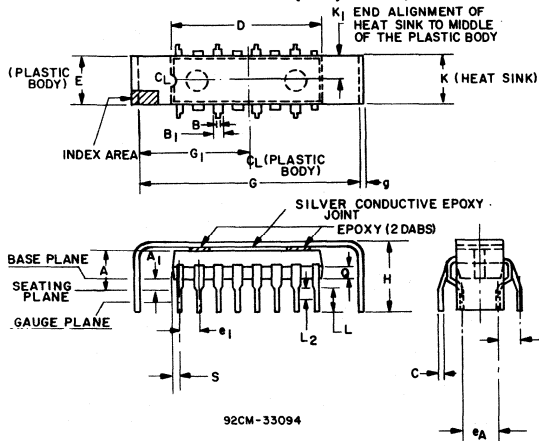
(Q) Suffix
Modified 16-Lead with Integral Bent Down Wing-Tab Heat Sink



92CM-25044R3

DIMENSIONS IN PARENTHESES ARE MILLIMETER EQUIVALENTS OF THE BASIC INCH DIMENSIONS

(QM) Suffix, 16-Lead Quad-In-Line Plastic with "Power Slab"



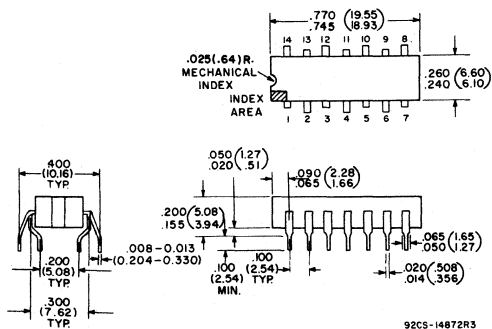
92CM-33094

SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
A	0.155	0.200		3.94	5.08
A1	0.020	0.050		0.51	1.27
B	0.014	0.020		0.356	0.508
B1	0.035	0.065		0.89	1.65
C	0.008	0.012	1	0.204	0.304
C1	0.085	0.105		2.41	2.67
D	0.745	0.785		18.93	19.93
E	0.240	0.260		6.10	6.60
e1	0.100 TP		.2	2.54 TP	
e2	0.200 TP		2.3	7.62 TP	
G	1.125 TP			2.858	
G1	0.537	0.587		13.64	14.91
g	0.030	0.036		0.76	0.91
H	0.350			8.89	
K	0.250	7		6.35	
K1	0.093	0.157		2.36	3.99
L	0.125	0.150		3.18	3.81
L1	0.000	0.030		0.000	0.76
N	16	5		16	
N1	0	6		0	
Q	0.040	0.075		1.02	1.90
S	0.015	0.060		0.39	1.52

- NOTES:
Refer to Rules for Dimensioning (JEDEC Publication No. 95) for Axial Lead Product Outlines.
- When this device is supplied solder-dipped, the maximum lead thickness (narrow portion) will not exceed 0.013" (0.33 mm).
 - Leads within 0.005" (0.12 mm) radius of True Position (TP) at gauge plane with maximum material condition and unit installed.
 - e1 applies in zone L1 when unit installed.
 - e2 applies to spread leads prior to installation.
 - N is the maximum quantity of lead positions.
 - N1 is the quantity of allowable missing leads.
 - Bulging to 0.260" (7.11 mm) permissible at points of debossing.

QUAD-IN-LINE PLASTIC PACKAGES

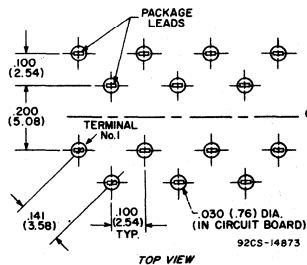
(W) Suffix, 14-Lead Staggered



92CS-14872R3

- NOTES:
1. Body width is measured 0.040" (1.02 mm) from top surface.
2. Seating plane defined as the junction of the angle with the narrow portion of the lead.
- Dimensions in parentheses are millimeter equivalents of the basic inch dimensions.

Recommended Mounting Hole Dimensions and Spacing



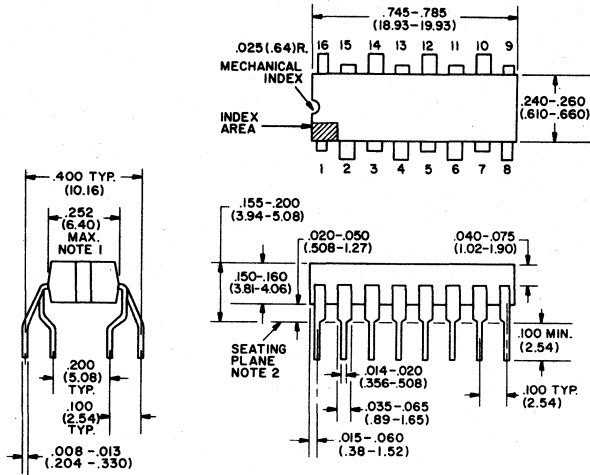
92CS-14873

Linear Integrated Circuits

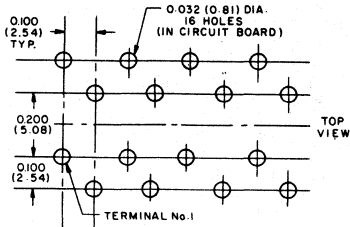
Dimensional Outlines

QUAD-IN-LINE PLASTIC PACKAGES

(W) Suffix, 16-Lead Staggered

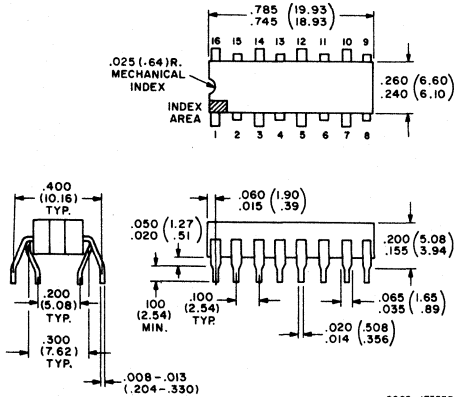


Recommended Mounting Hole Dimensions and Spacing

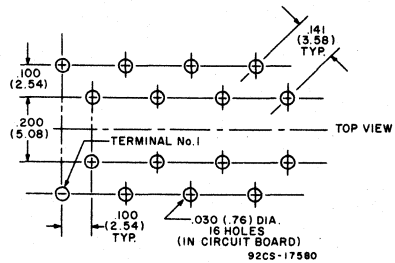


- NOTES:
1. Body width is measured 0.040" (1.02 mm) from top surface.
 2. Seating plane defined as the junction of the angle with the narrow portion of the lead.
- Dimensions in parentheses are millimeter equivalents of the basic inch dimensions.

(Q) Suffix, 16-Lead

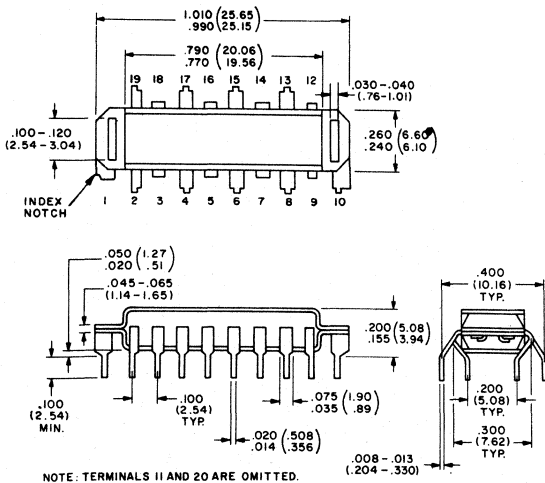


Recommended Mounting Hole Dimensions and Spacing

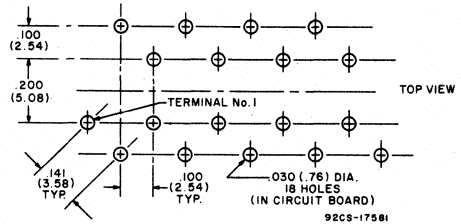


- NOTES:
1. Body width is measured 0.040" (1.02 mm) from top surface.
 2. Seating plane defined as the junction of the angle with the narrow portion of the lead.
- Dimensions in parentheses are millimeter equivalents of the basic inch dimensions.

20-Lead Shielded Plastic Package



Recommended Mounting Hole Dimensions and Spacing



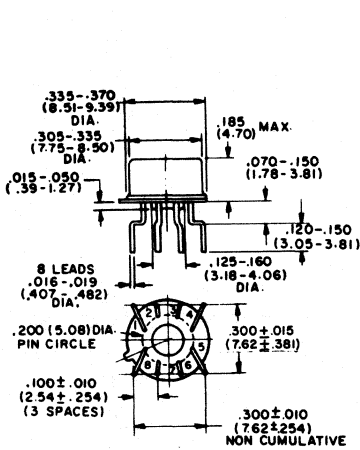
- NOTES:
1. Body width is measured 0.040" (1.02 mm) from top surface.
 2. Seating plane defined as the junction of the angle with the narrow portion of the lead.
- Dimensions in parentheses are millimeter equivalents of the basic inch dimensions.

Supplementary Information

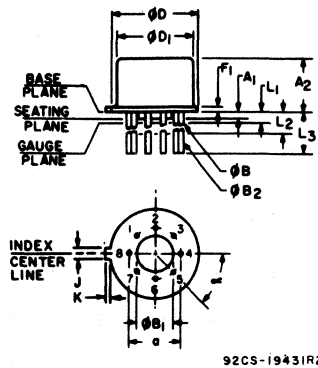
Dimensional Outlines

TO-5 STYLE PACKAGES

(S) Suffix, 8-Lead TO-5 Style with Dual-In-Line Formed Leads (DIL-CAN)



(T) Suffix (JEDEC MO-002-AL), 8-Lead TO-5 Style

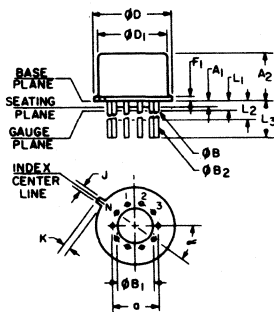


SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
a	0.200 TP		2	5.88 TP	
A ₁	0.010	0.050		0.26	1.27
A ₂	0.165	0.185		4.20	4.89
øB	0.016	0.019	3	0.407	0.482
øB ₁	0.125	0.160		3.18	4.06
øB ₂	0.016	0.021	3	0.407	0.533
øD	0.335	0.370		8.51	9.39
øD ₁	0.305	0.335		7.75	8.50
F ₁	0.020	0.040		0.51	1.01
j	0.028	0.034		0.712	0.863
k	0.029	0.045	4	0.74	1.14
L ₁	0.000	0.050	3	0.00	1.27
L ₂	0.250	0.500	3	6.4	12.7
L ₃	0.500	0.562	3	12.7	14.27
α	45° TP			45° TP	
N	8		6	8	
N ₁	3		5	3	

NOTES

- Refer to JEDEC Publication No 95 for Rules for Dimensioning Axial Lead Product Outlines.
- Leads at gauge plane within 0.007" (0.178 mm) radius of True Position (TP) at maximum material condition.
- øB applies between L₁ and L₂. øB₂ applies between L₂ and 0.500" (12.70 mm) from seating plane. Diameter is uncontrolled in L₁ and beyond 0.500" (12.70 mm).
- Measure from Max. øD.
- N₁ is the quantity of allowable missing leads.
- N is the maximum quantity of lead positions.

(T) Suffix (JEDEC MO-006-AF), 10-Lead TO-5 Style



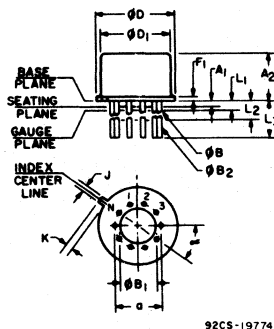
SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
a	0.230 TP		2	5.84 TP	
A ₁	0	0		0	0
A ₂	0.165	0.185		4.19	4.70
øB	0.016	0.019	3	0.407	0.482
øB ₁	0	0		0	0
øB ₂	0.016	0.021	3	0.407	0.533
øD	0.335	0.370		8.51	9.39
øD ₁	0.305	0.335		7.75	8.50
F ₁	0.020	0.040		0.51	1.01
j	0.028	0.034		0.712	0.863
k	0.029	0.045	4	0.74	1.14
L ₁	0.000	0.050	3	0.00	1.27
L ₂	0.250	0.500	3	6.4	12.7
L ₃	0.500	0.562	3	12.7	14.27
α	36° TP			36° TP	
N	10		6	10	
N ₁	1		5	1	

NOTES:

- Refer to Rules for Dimensioning Axial Lead Product Outlines.
- Leads at gauge plane within 0.007" (0.178 mm) radius of True Position (TP) at maximum material condition.
- øB applies between L₁ and L₂. øB₂ applies between L₂ and 0.500" (12.70 mm) from seating plane. Diameter is uncontrolled in L₁ and beyond 0.500" (12.70 mm).
- Measure from Max. øD.
- N₁ is the quantity of allowable missing leads.
- N is the maximum quantity of lead positions.

92CS-15835

(T) Suffix (JEDEC MO-006-AG), 12-Lead TO-5 Style



SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
a	0.230		2	5.84 TP	
A ₁	0	0		0	0
A ₂	0.165	0.185		4.19	4.70
øB	0.016	0.019	3	0.407	0.482
øB ₁	0	0		0	0
øB ₂	0.016	0.021	3	0.407	0.533
øD	0.335	0.370		8.51	9.39
øD ₁	0.305	0.335		7.75	8.50
F ₁	0.020	0.040		0.51	1.01
j	0.028	0.034		0.712	0.863
k	0.029	0.045	4	0.74	1.14
L ₁	0.000	0.050	3	0.00	1.27
L ₂	0.250	0.500	3	6.4	12.7
L ₃	0.500	0.562	3	12.7	14.27
α	30° TP			30° TP	
N	12		6	12	
N ₁	1		5	1	

NOTES:

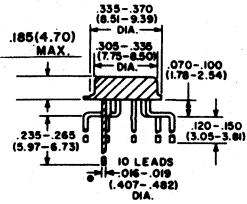
- Refer to Rules for Dimensioning Axial Lead Product Outlines.
- Leads at gauge plane within 0.007" (0.178 mm) radius of True Position (TP) at maximum material condition.
- øB applies between L₁ and L₂. øB₂ applies between L₂ and 0.500" (12.70 mm) from seating plane. Diameter is uncontrolled in L₁ and beyond 0.500" (12.70 mm).
- Measure from Max. øD.
- N₁ is the quantity of allowable missing leads.
- N is the maximum quantity of lead positions.

Linear Integrated Circuits

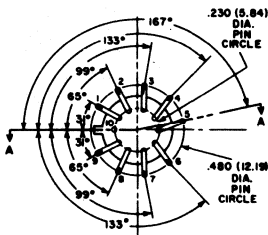
Dimensional Outlines

TO-5 STYLE PACKAGE (Cont'd)

(V) Suffix
10 Formed Leads Radially
Arranged TO-5 Type
(Available in 8 and
12-lead versions)

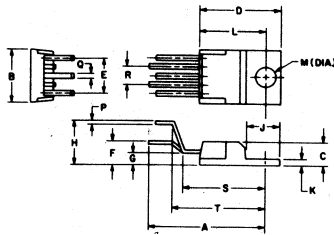


92CS-14638R2



TO-220 STYLE (VERSA-V) PLASTIC PACKAGE

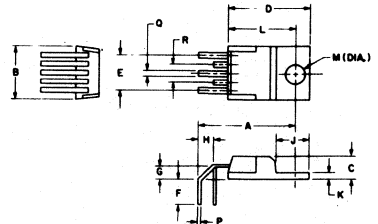
VERTICAL MOUNT



92CS-3066R1

SYMBOL	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
A	0.876	0.896	22.25	22.75
B	0.396	0.408	10.06	10.36
C	0.173	0.182	4.395	4.622
D	0.604	0.619	15.35	15.72
E	0.263	0.273	6.681	6.934
F	0.168	0.188	4.268	4.775
G	0.100	0.104	2.540	2.641
H	0.320	0.340	8.128	8.638
J	0.246	0.254	6.249	6.451
K	0.046	0.054	1.169	1.371
L	0.496	0.508	12.60	12.90
M	0.140	0.150	3.556	3.810
N	5		5	
P	0.015	0.020	0.381	0.406
Q	0.033	0.040	0.839	1.016
R	0.129	0.139	3.277	3.530
S	0.600	0.630	15.24	16.00
T	0.680	0.710	17.27	18.03

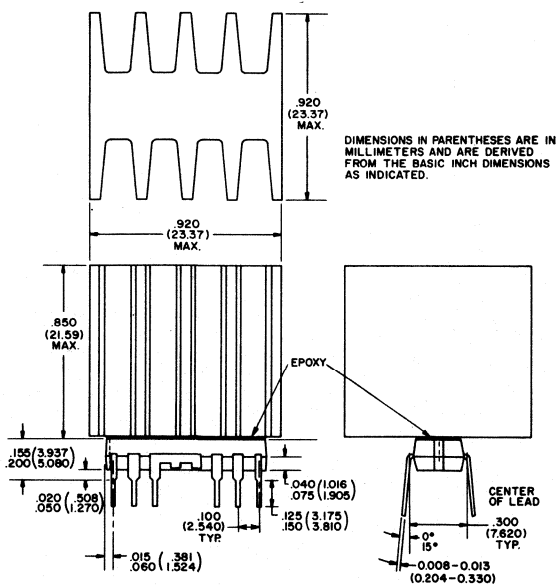
HORIZONTAL MOUNT (M Suffix)



92CS-3066R1

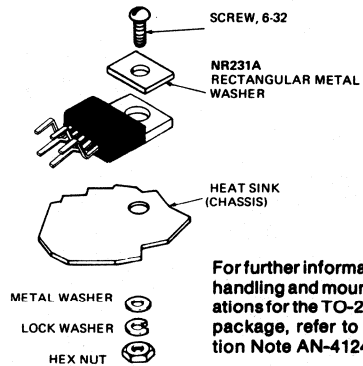
SYMBOL	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
A	0.726	0.746	18.44	18.94
B	0.396	0.408	10.06	10.36
C	0.173	0.182	4.395	4.622
D	0.604	0.619	15.35	15.72
E	0.263	0.273	6.681	6.934
F	0.221	0.251	5.614	6.375
G	0.100	0.104	2.540	2.641
H	0.143	0.163	3.633	4.140
J	0.246	0.254	6.249	6.451
K	0.046	0.054	1.169	1.371
L	0.496	0.508	12.60	12.90
M	0.140	0.150	3.556	3.810
N	5		5	
P	0.015	0.020	0.381	0.406
Q	0.033	0.040	0.839	1.016
R	0.129	0.139	3.277	3.530

(EM) Suffix (Dual-in-Line) Modified 16-Lead with Integral Heat Sink



92CM-33104

Suggested Hardware and Mounting Arrangement



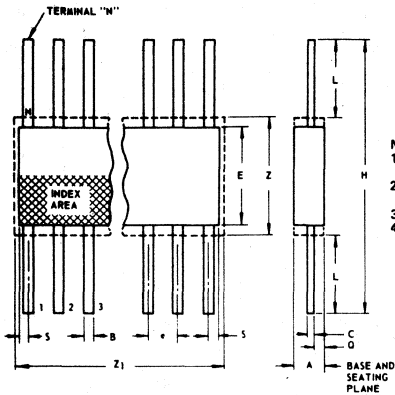
For further information regarding handling and mounting considerations for the TO-220 style plastic package, refer to RCA Application Note AN-4124.

NOTE: MAXIMUM TORQUE APPLIED TO MOUNTING FLANGE IS 8 in.-lb. (0.09 kgf-m)

92CS-29194R1

CERAMIC FLAT PACKS

(K) Suffix (JEDEC MO-004-AF), 14-Lead

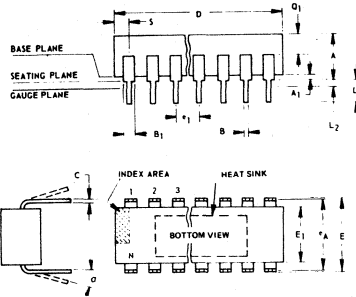


- NOTES:**
1. Refer to Rules for Dimensioning (JEDEC Publication No. 95) for Axial Lead Product Outlines.
 2. Leads within .005" (0.12 mm) radius of True Position (TP) at maximum material condition.
 3. N is the maximum quantity of lead positions.
 4. Z and Z₁ determine a zone within which all body and lead irregularities lie.

SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
A	0.008	0.100		0.21	2.54
B	0.015	0.019	1	0.381	0.482
C	0.003	0.006	1	0.077	0.152
e	0.050 TP		2	1.27 TP	
E	0.200	0.300		5.1	7.6
H	0.600	1.000		15.3	25.4
L	0.150	0.350		3.9	8.8
N	14		3	14	
Q	0.005	0.050		0.13	1.27
S	0.000	0.050		0.00	1.27
Z	0.300		4	7.62	
Z ₁	0.400		4	10.16	

92SS 4300R3

(P) Suffix 16-Lead "Power Slab" Dual-In-Line Plastic Package

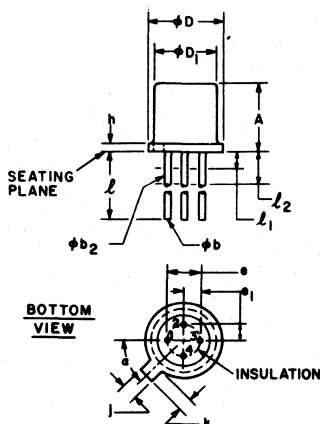


- NOTES:**
- Refer to Rules for Dimensioning (JEDEC Publication No. 95) for Axial Lead Product Outlines.
1. When this device is supplied solder-dipped, the maximum lead thickness (narrow portion) will not exceed 0.013" (0.33 mm).
 2. Leads within 0.005" (0.12 mm) radius of True Position (TP) at gauge plane with maximum material condition and unit installed.
 3. e_A applies in zone L₂ when unit installed.
 4. α applies to spread leads prior to installation.
 5. N is the maximum quantity of lead positions.
 6. N₁ is the quantity of allowable missing leads.

SYMBOL	INCHES		NOTE	MILLIMETERS	
	MIN.	MAX.		MIN.	MAX.
A	0.155	0.200		3.94	5.08
A ₁	0.020	0.050		0.51	1.27
B	0.014	0.020		0.356	0.508
B ₁	0.035	0.065		0.89	1.65
C	0.008	0.012	1	0.204	0.304
D	0.745	0.785		18.93	19.93
E	0.300	0.325		7.62	8.25
E ₁	0.240	0.260		6.10	6.60
e ₁	0.100 TP		2	2.54 TP	
e _A	0.300 TP		2, 3	7.62 TP	
L	0.125	0.150		3.18	3.81
L ₂	0.000	0.030		0.000	0.76
α	0°	15°	4	0°	15°
N	16		5	16	
N ₁	0		6	0	
Q ₁	0.040	0.075		1.02	1.90
S	0.015	0.060		0.39	1.52

92CM-32023

JEDEC TO-72 Package



SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	0.170	0.210	4.32	5.33	2
φb	0.016	0.021	0.406	0.533	
φb ₂	0.016	0.019	0.406	0.483	2
φD	0.209	0.230	5.31	5.84	
φD ₁	0.178	0.195	4.52	4.95	4
e	0.100 T.P.		2.54 T.P.		
e ₁	0.050 T.P.		1.27 T.P.		4
h	0.030		0.762		
i	0.036	0.046	0.914	1.17	3
k	0.028	0.048	0.711	1.22	
l	0.500		12.70		2
l ₁	0.050		1.27		
l ₂	0.250		6.35		2
α	45° T.P.		45° T.P.		

- Note 1** (Four leads) Maximum number leads omitted in this outline, "none" (0). The number and position of leads actually present are indicated in the product registration. Outline designation determined by the location and minimum angular or linear spacing of any two adjacent leads.
- Note 2** (All leads) φb₂ applies between l₁ and l₂. φb applies between l₂ and 500" (12.70 mm) from seating plane. Diameter is uncontrolled in l₁ and beyond 500" (12.70 mm) from seating plane.
- Note 3** Measured from maximum diameter of the product.
- Note 4** Leads having maximum diameter .019" (0.483 mm) measured in gaging plane .054" (1.37 mm) + .001" (0.025 mm) - .000" (0.000 mm) below the seating plane of the product shall be within .007" (0.178 mm) of their true position relative to a maximum width tab.
- Note 5** The product may be measured by direct methods or by gage.
- Note 6** Tab centerline.

92CS-17444 RI

Abstracts of Application Notes

AN-3193 9 pages
Application Considerations for the RCA-3N128 VHF MOS Field-Effect Transistor

This Note describes applications and vhf circuit considerations for a high-frequency n-channel MOS field-effect transistor, the RCA 3N128. Biasing requirements and basic circuit configurations are discussed, and selection of the optimum operating point and methods of automatic gain control are explained. The cross-modulation and intermodulation distortion characteristics of the 3N128 MOS transistor are compared to those of bipolar transistors, and procedures are given for the design of a practical vhf amplifier that uses the 3N128.

AN-3341 3 pages
VHF Mixer Design Using the RCA-3N128 MOS Transistor

The 3N128 is a vhf MOS field-effect transistor suitable for use throughout the vhf band (30 to 300 MHz) as an amplifier, mixer, or oscillator. This Note discusses some of the design criteria pertinent to the construction of MOS mixers, and presents an example of a complete vhf MOS converter.

AN-3452 7 pages
Chopper Circuits Using RCA MOS Field-Effect Transistors

Although electromechanical relays have long been used to convert low-level dc signals into ac signals or for multiplex purposes, relays are seriously limited with respect to life, speed, and size. Conventional (bipolar) transistors overcome the inherent limitations of relays, but introduce new problems of offset voltage and leakage currents. This Note describes the use of MOS field-effect transistors in solid-state chopper and multiplex designs that have the long life, fast speed, and small size of bipolar-transistor choppers, but that eliminate their inherent offset-voltage and leakage-current problems.

AN-3453 6 pages
An FM Tuner Using an RCA-40468 MOS-Transistor RF Amplifier

This Note describes an FM tuner that incorporates a MOS field-effect transistor as the rf amplifier, and shows how the MOS transistor is instrumental in minimizing the spurious responses normally found in FM receivers.

AN-3535 6 pages
An FM Tuner Using Single-Gate MOS Field-Effect Transistors as RF Amplifier and Mixer

Selection of the transistors for use in FM-tuner stages involves consideration of such device characteristics as spurious response, dynamic range, noise immunity, gain, and feedthrough capacitance. MOS field-effect transistors are especially suitable for use in FM rf-amplifier and mixer stages because of their inherent superiority for spurious-response rejection and signal-handling capability. This Note describes an FM tuner that uses an RCA-40468 MOS transistor as the rf amplifier and an RCA-40559 MOS transistor as the mixer.

AN-4018 5 pages
Design of Gate-Protected MOS Field-Effect Transistors

MOS (metal-oxide-semiconductor) field-effect transistors are in demand for rf-amplifier applications because their transfer characteristics make possible significantly better performance than that experienced with other solid-state devices. Unless equipped with gate protection, however, MOS transistors require careful handling to prevent static discharges from rupturing the dielectric material that separates the gate from the channel. This Note describes the design of dual-gate MOS field-effect transistors that use a built-in signal-limiting diode structure to provide an effective short circuit to static discharge and limit high potential buildup across the gate insulation.

AN-4125 7 pages
MOS/FET Biasing Techniques

Field-effect transistors are applied in rf amplifiers, and mixers, if and audio amplifiers, electrometer and memory circuits, attenuators, and switching circuits. The dual-gate MOS/FET appears to be particularly useful in rf stages because of low feedback capacitance, high transconductance, and superior cross modulation with automatic-gain-control capability. The rules for biasing FET's vary slightly depending on type. However, most possibilities are covered in this Note through examination of the biasing of a single-gate, a junction-gate, and a dual-gate transistor. Substrate biasing and biasing to compensate for temperature variations are also discussed.

AN-4431 8 pages
RF Applications of the Dual-Gate MOS/FET Up to 500 MHz

The dual-gate protected, metal-oxide silicon, field-effect transistor (MOS FET) is especially useful for high-frequency applications in rf amplifier circuits. The dual-gate feature permits the design of simple AGC circuitry requiring very low power. The integrated diodes protect the gates against damage due to static discharge that may develop during handling and usage. This Note describes the use of the RCA-3N200 dual-gate MOS FET in rf applications. The 3N200 has good power gain and a low noise factor at frequencies up to 500 MHz, offers especially good cross-modulation performance, and has a wide dynamic range; its low-feedback capacitance provides stable performance without neutralization.

AN-4590 16 pages
Using MOS/FET Integrated Circuits in Linear Circuit Applications

A brief review of MOS/FET IC device theory is given, and some linear circuit applications are surveyed. Theory discussed includes gate protection and electrical requirements. Applications include choppers, attenuators, constant-current sources, general-purpose amplifier circuits, and rf amplifiers, oscillators, and mixers.

ICAN-4072 8 pages
Applications of the RCA-CA3048 Integrated-Circuit Amplifier Array

The RCA-CA3048 integrated circuit, an array of four identical amplifiers, each with independent inputs and outputs, all on a single monolithic silicon chip, has an operating and storage temperature range of -25°C to +85°C. Each amplifier in the low-noise array has a typical open-loop gain of 58 dB and input impedance of 90,000 ohms. The gain-frequency response, stability, output swing versus supply voltage, and noise of the device are discussed. Circuit applications include Hartley and Colpitts Oscillators, astable multivibrators, a 4-channel linear mixer, a driver for a 600-ohm balanced line, and a gain-controlled amplifier.

ICAN-5015 15 pages
Application of the RCA-CA3008 and CA3010 Integrated-Circuit Operational Amplifiers

This Note describes the circuit arrangement, lists the performance characteristics, explains the major design considerations, and discusses typical applications of the CA3008 and CA3010 operational amplifiers. These amplifiers are silicon monolithic integrated circuits designed to operate from two symmetrical low- or medium-level dc power supplies (at supply voltages in the range from +3 volts to +6 volts).

Abstracts of Application Notes (Cont'd)

ICAN-5022 26 pages
Application of the RCA-CA3004, CA3005, and CA3006 Integrated-Circuit RF Amplifiers

The CA3004, CA3005, and CA3006 rf amplifiers are discussed. These silicon-epitaxial monolithic integrated circuits are designed to operate from low or medium levels of dc supply voltage, over a range of ambient temperatures from -55°C to $+125^{\circ}\text{C}$, and at frequencies from dc to 100 MHz. They may be used with external tuned-circuit, transformer, or resistive load impedances to provide wide- or narrow-band amplification, mixing, limiting, product detection, frequency generation, and generation of pulse or digital waveforms.

ICAN-5030 11 pages
Application of the RCA-CA3000 Integrated-Circuit DC Amplifier

This Note describes the RCA-CA3000 dc amplifier, a stabilized and compensated differential amplifier that has push-pull outputs, high-impedance (0.1-megohm) inputs, and gain of approximately 30 dB at frequencies up to one MHz. Its useful frequency response can be increased to several tens of megahertz by the use of external resistors or coils. The CA3000 can be used as a single switch (with pedestal), a squelchable audio amplifier (with suppressed switching transient), a modulator, a mixer or a product detector. When suitable external components are added, it can also be used as an oscillator, a one-shot multivibrator, or a trigger with controllable hysteresis.

ICAN-5036 9 pages
Application of the RCA-CA3002 Integrated-Circuit IF Amplifier

The RCA-CA3002 integrated-circuit if amplifier described in this Note is a balanced differential amplifier that can be used with either a single-ended or a push-pull input and can provide either a direct-coupled or a capacitance-coupled single-ended output. Its applications include RC-coupled if amplifiers that use the internal silicon output-coupling capacitor, video amplifiers that use an external coupling capacitor, envelope detectors, product detectors, and various trigger circuits.

ICAN-5037 4 pages
Application of the RCA-CA3007 Integrated-Circuit Audio Amplifier

This Application Note describes the RCA-CA3007 audio driver, a balanced differential configuration with either a single-ended or a differential input and two push-pull emitter-follower outputs. The circuit features all-monolithic silicon epitaxial construction, and is intended for use as a direct-coupled driver in a class B audio amplifier which exhibits both gain and operating-point stability over the temperature range from -55 to $+125^{\circ}\text{C}$.

ICAN-5038 8 pages
Application of the RCA-CA3001 Integrated-Circuit Video Amplifier

The CA3001 silicon monolithic integrated circuit is designed for use in intermediate-frequency or video amplifiers at frequencies up to 20 MHz and in Schmitt-trigger applications. This integrated circuit can be gated, and gain control can be applied. The CA3001 incorporates all-monolithic silicon epitaxial construction designed for operation at ambient temperatures from -55 to $+125^{\circ}\text{C}$, balanced differential-amplifier configuration with low-impedance double-ended input, and a built-in temperature-compensating network for gain or dc operating-point stability over the temperature range from -55 to $+125^{\circ}\text{C}$.

ICAN-5213 6 pages
Application of the RCA CA3015 and CA3016 Integrated-Circuit Operational Amplifiers

The integrated-circuit operational amplifiers CA3015 and CA3016 are identical in circuit configuration to the CA3008 and CA3010, but have an improved device breakdown voltage that permits operation from +12-volt supplies as well as from +6-volt or +3-volt supplies. This Note describes the operating characteristics of the CA3015 and CA3016 at +12 volts, and discusses applications that take advantage of the higher gain-bandwidth product and increased output signal swing obtained at the higher voltages: a 50-dB amplifier; a 10-dB, 42-MHz amplifier; a twin-T bandpass amplifier; and a voltage-follower.

ICAN-5269 7 pages
Integrated Circuits for FM Broadcast Receivers

This Note describes several approaches to FM receiver design using silicon monolithic integrated circuits. The tuner section is described first, and then the if-amplifier and detector sections. Performance characteristics are described where applicable. The FM receivers discussed are designed for use from a +9-volt supply. The key to design simplicity is the use of the RCA multifunction integrated circuits CA3005, CA3012, and CA3014. The CA3005 may be used as a cascode rf amplifier, a differential rf amplifier, a mixer-oscillator, and an if amplifier; the CA3012 and CA3014 perform if amplification, limiting, detection, and preamplification.

ICAN-5296 5 pages
Application of the RCA-CA3018 Integrated-Circuit Transistor Array

The CA3018 integrated circuit consists of four silicon epitaxial transistors produced by a monolithic process on a single chip mounted in a 12-lead TO-5 package. The four active devices, two isolated transistors plus two transistors with an emitter-base common connection, are especially suitable for applications in which closely matched device characteristics are required, or in which a number of active devices must be interconnected with non-integrable components such as tuned circuits, large-value resistors, variable resistors, and microfarad bypass capacitors. Such areas of application include if, rf (through 100 MHz), video, agc, audio, and dc amplifiers.

ICAN-5299 6 pages
Application of the RCA-CA3019 Integrated-Circuit Diode Array

The CA3019 integrated-circuit diode array provides four diodes internally connected in a diode-quad arrangement plus two individual diodes. Its applications include gating, mixing, modulating, and detecting circuits. Because all the diodes are fabricated simultaneously on a single silicon chip, they have nearly identical characteristics, and their parameters track each other with temperature variations. Consequently, the CA3019 is particularly useful in circuit configurations that require either a balanced diode bridge or identical diodes.

ICAN-5337 10 pages
Application of the RCA-CA3028A and CA3028B Integrated-Circuit RD Amplifiers in the HF and VHF Ranges

The CA3028A and CA3028B monolithic-silicon integrated circuits are single-stage differential amplifiers intended for service in communications systems operating at frequencies up to 100 MHz with single power supplies. This Note provides technical data and recommended circuits for use of the CA3028A and CA3028B in rf amplifiers, autodyne converters, if amplifiers, and limiters. The CA3028A and CA3028B are suitable for use in a wide range of applications in dc, audio, and pulse amplifier service; they have been used as sense amplifiers, preamplifiers for low-level transducers, and dc differential amplifiers.

Abstracts of Application Notes (Cont'd)

ICAN-5338 14 pages
Application of the RCA-CA3021, CA3022, and CA3023 Integrated-Circuit, Wideband Amplifiers

The CA3021, CA3022, and CA3023 integrated circuits are multipurpose high-gain amplifiers designed for use in video and AM or FM if stages in single-power-supply systems. Specifically, they can be used in video amplifiers operating at frequencies through 30 MHz. AM and FM if amplifiers, and buffer amplifiers in which an isolation capability greater than 60 dB at 1 MHz is desired.

ICAN-5380 7 pages
Integrated-Circuit Frequency-Modulation IF Amplifiers

The discussion in this Note shows that the simplest approach to the use of the CA3012 and CA3028 integrated circuits in FM if-amplifier strips is to replace each stage in present discrete-transistor if strips with a differential amplifier. This integrated-circuit approach requires a minimum of re-engineering because a cascade of individually tuned if stages is used. From a performance point of view, this approach results in better AM rejection than that obtained with discrete circuits because of the inherent limiting achieved with the differential-amplifier configuration.

ICAN-5766 8 pages
Application of the RCA-CA3020 and CA3020A Integrated-Circuit Multipurpose Wideband Power Amplifiers

The CA3020 and CA3020A integrated circuits are multipurpose, multifunction power amplifiers designed for use as power-output amplifiers and driver stages in portable and fixed communications equipment and in ac servo-control systems. The flexibility of these circuits and the high-frequency capabilities of the circuit components make these types suitable for a wide variety of applications such as broadband amplifiers, video empliers, and video line drivers. Voltage gains of 60 dB or more are available, with a 3-dB bandwidth of 8 MHz. Applications covered include audio, wideband, and driver amplifiers.

ICAN-5841 4 pages
Feedback-Type Volume-Control Circuits for RCA-CA3041 and CA3042 Integrated Circuits

This Note describes feedback-type volume controls for use with RCA-CA3041 and CA3042 integrated circuits in television receivers. In television sets using these integrated circuits, the volume control is often located remote from the amplifier. The long leads required in such a configuration sometimes pick up undesirable signals that, in turn, cause the system to exhibit hum and noise at low volume levels. The proposed feedback-type volume control reduces hum and noise pick-up by reducing the gain of the system rather than the signal level, and thus eliminates the cost of shielding the leads.

ICAN-6048 12 pages
Some Applications of a Programmable Power Switch/Amplifier

The CA3094 monolithic programmable power switch/amplifier IC consists of a high-gain preamplifier driving a power-output amplifier stage. It can deliver average power of 3 watts or peak power of 10 watts to an external load, and can be operated from either a single or dual power supply. This Note briefly describes the characteristics of the CA3094, and illustrates its use in applications such as class A instrumentations and power amplifiers, class A driver-amplifiers for complementary power transistors, wide-frequency-range power multivibrators, current- or voltage-controlled oscillators, comparators (threshold detectors), voltage regulators, analog timers (long time delays), alarm systems, motor-speed controllers, thyristor-firing circuits, battery-charge regulator circuits, and ground-fault-interupter circuits.

ICAN-6077 12 pages
An IC Operational-Transconductance-Amplifier (OTA) with Power Capability

This Note defines the OTA and describes two circuits of this type, the CA3080 and the CA3094. The single, highly linear operational-transconductance-amplifier, the CA3080, because of its extremely linear transconductance characteristics with respect to amplifier bias current, has gained wide acceptance as a gain-control block. The CA3094 improved on the performance of the CA3080 through the addition of a pair of transistors; these transistors extended the current-carrying capability to 300 milliamperes, peak. The CA3094, is useful in an extremely broad range of circuits in consumer and industrial applications; this Note describes only a few of the many consumer applications.

ICAN-6157 12 pages
Applications of the CA3085-Series Monolithic IC Voltage Regulators

This Note describes the basic circuit of the CA3085-series devices and some typical applications that include a high-current regulator, constant-current regulators, a switching regulator, a negative-voltage regulator, a dual-tracking regulator, high-voltage regulators, and various methods of providing current limiting. A circuit in which the CA3085 is used as a general-purpose amplifier is also shown.

ICAN-6182 32 pages
Features and Applications of RCA Integrated-Circuit Zero-Voltage Switches (CA3058, CA3059, and CA3079)

CA3058, CA3059, and CA3079 zero-voltage switches are monolithic integrated circuits designed primarily for use as trigger circuits for thyristors in many highly diverse ac power-control and power-switching applications. This Note discusses the operation and application of these circuits.

ICAN-6247 8 pages
Application of the CA3126Q Chroma-Processing IC Using Sample-and-Hold Circuit Techniques

This Note describes the CA3126Q monolithic integrated circuit intended for use in processing the chrominance signal in a color television receiver. In performing the functions of color subcarrier regeneration and chroma control, emphasis has been placed on utilizing all the information available in the signal so as to approach ultimate system performance capability, while at the same time substantially reducing the number of external components and adjustments.

ICAN-6257 8 pages
Application of the CA3089E FM-IF Subsystem

The CA3089E, is an FM-IF subsystem intended for use in FM receiver applications. In addition to the amplifier-limiter and quadrature detector sections, the CA3089E provides such auxiliary functions as mute, AFC output, tuning-meter output, and delayed rf-AGC. This Note briefly describes each circuit section and discusses practical aspects of designing with this device.

ICAN-6259 10 pages
Integrated-Circuit Stereo Decoder Using the CA3090AQ Stereo Multiplex Demodulator

The CA3090AQ integrated circuit provides features heretofore unavailable to the receiver designer. This device needs only a single tuning adjustment, which reduces to a minimum the manual effort during assembly; the phase-locked loop maintains performance under conditions of temperature variations, humidity, and aging. The compactness of the CA3090AQ and of the required external components, added to the other attributes, makes this stereo decoder a significant advancement in the state of the art of stereo decoder designs.

Abstracts of Application Notes (Cont'd)

ICAN-6302 9 pages
Description and Application of the RCA-CA3120E Integrated-Circuit TV-Signal Processor

The CA3120E is a 16-pin, dual-in-line monolithic-silicon integrated circuit that processes a video signal and provides the following outputs: non-inverted video output; noise-processed, inverted video output; dual-polarity, composite synchronization signals; and automatic gain-control signals (agc). The IC, which can be used in color or monochrome TV receivers, requires a single-polarity power supply (positive) and includes impulse-noise inversion and delay circuits that reduce the deleterious effects of impulse noise in the receiver agc and synchronization (sync) circuits. Standard agc strobing techniques are also used. The agc and impulse-noise thresholds are automatically set and require no controls. The if maximum-gain bias and the tuner agc delay may be adjusted for optimum TV-receiver performance; the time constant for the sync-separator input can also be optimized by the set designer.

ICAN-6303 16 pages
A Single IC for the Complete PIX-IF-System in TV Receivers

The CA3068 linear integrated circuit is a PIX-IF-subsystem in a shielded, quad-formed, dual-in-line, 20-lead, plastic package. This package contains all the active devices and most of the passive elements necessary for a high performance, PIX-IF-system for a TV receiver. This Note describes the receiver functions performed by the CA3068, and its application to color and monochrome TV receivers.

ICAN-6668 16 pages
Applications of the CA3080 and CA3080A High-Performance Operational Transconductance Amplifiers

The CA3080 and CA3080A are similar in generic form to conventional operational amplifiers, but differ sufficiently to justify an explanation of their characteristics. This class of operational amplifier includes not only the usual differential input terminals, but an additional control terminal that enhances the device's flexibility. This Note describes the operation of the OTA and features various circuits using it.

For example, communications and industrial applications, including modulators, multiplexers, sample-and-hold circuits, gain control circuits and micropower comparators, are shown and discussed. These circuits show the operation of the OTA in conjunction with CMOS devices as post-amplifiers.

ICAN-6728 8 pages
Application of the CA3134E Sound IF and Output Subsystems in Television Receivers

In the CA3134, the sound IF and audio output subsystems for color or black-and-white television receivers are combined in a single monolithic integrated circuit. The consolidation of these functions into an integrated circuit minimizes the number of components needed and reduces the area of the printed-circuit board necessary for this portion of a television receiver. This consolidation also permits a reduction in manufacturers' component inventories and simplifies field servicing. Circuit characteristics, functions, and applications are discussed.

ICAN-6732 8 pages
Measurement of Burst ("Popcorn") Noise in Linear Integrated Circuits

The advent in recent years of very high-gain operational amplifiers operating in the $1/f$ noise-frequency spectrum has placed emphasis on the need for very low-noise devices. This need is particularly true for operational amplifiers which have either low-offset characteristics and/or offset-null capability.

The traditional methods used to select very-low-noise devices for operational amplifiers involve the measurement of either spot or wideband (≈ 10 kHz) noise figures in the $1/f$ frequency range (10 Hz to 10 kHz) at various source resistances. This type of measurement, however, only provides an indication of the average noise power at the measurement frequency and does not reveal the burst ("popcorn") noise characteristics of the Device Under Test (DUT). This Note describes in detail a test that will detect burst noise.

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